СПРАВОЧНИК

на основе vrt 2008

ЗАРУБЕЖНЫЕ

МИКРОСХЕМЫ ТРАНЗИСТОРЫ ТИРИСТОРЫ ДИОДЫ+SMD



Издание 4-е, переработанное и дополненное

характеристики
производители
цоколевка
аналоги

0...9

электронные компоненты
НиТ издательство

vrt 0...µ volume 2

vergleichstabelle
comparison table
table d' équivalence
tabella comparativa
tabla comparativa

transistor
thyristor
smd code
diode
ic
linear
digital
analog



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Серия «Электронные компоненты»

Перед вами российское издание самого популярного в Европе справочника vrt по микросхемам, транзисторам, тиристорам, диодам, названия которых начинаются с цифр. При составлении справочника использовалась техническая документация ведущих фирм-производителей электронных полупроводниковых приборов, систематизирована достоверная информация. Именно систематизация является сильной стороной этого справочника.

Для читателя будут полезны в работе краткие характеристики и аналоги радиоэлектронных компонентов. Вводная часть справочника представлена на русском и английском языках.

Справочник предназначен, в первую очередь, для инженерно-технического персонала, занимающегося сервисным обслуживанием электронной техники и, надеемся, будет полезен радиолюбителям.

Рекомендуем приобрести аналогичный справочник по ИМС, транзисторам, тиристорам, диодам, названия которых начинаются с букв A...Z (в двух томах).

Все материалы, помещенные в данной книге, многократно проверенны. Но вероятность появления технических ошибок все равно существует. Издательство не несет ответственности, связанной с применением информации данной книги.



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Как пользоваться справочником

Основой справочника является таблица «Параметры электронных полупроводниковых приборов и интегральных микросхем», в которой 6 колонок.

Тип (Колонка 1)

В колонке приводится фирменное обозначение дискретного прибора либо интегральной схемы, соответствующее документации изготовителя, которое в полной или сокращенной форме наносится на корпус прибора. Старые фирменные названия полупроводниковых элементов сохранены без изменений.

Структура (Колонка 2)

В колонке приводится краткое описание полупроводниковых приборов, их структура и принадлежность к одному из подклассов (диод, транзистор и т.д.).

Используемые сокращения:

C-Di ..... диод с изменяемой емкостью p-n перехода (варикап)
CMOS-IC..... микросхема на комплементарных МОП-транзисторах
CMOS-Logic ..... логика на комплементарных МОП-транзисторах
Diac ..... симметричный диодный тиристор, симметричный динистор
EEPROM-IC..... ПЗУ
FET ..... полевой транзистор
F-Thy ..... запираемый тиристор
F-Thy+Di ..... тиристор для TV строчной развертки
GaAs..... арсенид галлия
Ge-Di ..... германиевый диод
Ge-N..... германиевый n-p-n транзистор
Ge-P ..... германиевый p-n-p транзистор
GTO-Thy..... двухоперационный диодный тиристор, двухопер. тринистор
Hybrid-Z-IC..... ГИС
MOS ..... металл-оксид-кремний, металл-оксид-полупроводник (МОП-структура)
MOS-FET-d ..... полевой МОП-транзистор со встроенным каналом
MOS-FET-e..... полевой МОП-транзистор с индуцированным каналом
MOS-N-FET..... МОП-структура с n каналом
N-FET ..... полевой транзистор с n каналом
Opto ..... оптоэлектронный компонент
PIN-Di ..... pin диод
PUT ..... программируемый однопереходной транзистор
P-FET..... полевой транзистор с p каналом

Ref-Di. . . . . выпрямительный диод
SAW-Filter. . . . . фильтр на поверхностных акустических волнах
SBS . . . . . система коммерческой спутниковой связи
Se-Di. . . . . селеновый диод
Si-Br . . . . . кремниевый мостовой выпрямитель
Si-Di . . . . . кремниевый диод
Si-N. . . . . кремниевый n-p-n транзистор
Si-N-Darl . . . . . кремниевый n-p-n транзистор Дарлингтона
Si-P . . . . . кремниевый p-n-p транзистор
Si-P-Darl . . . . . кремниевый p-n-p транзистор Дарлингтона
Si-St . . . . . кремниевый, со стабильными параметрами
SUS. . . . . кремниевый однонаправленный переключатель
Tetrode. . . . . тетрод
Thy . . . . . тиристор
Thy-Br . . . . . тиристорный шунт (мостовой)
Triac . . . . . симистор
Trigger-Di . . . . . триггер-диод
TTL-Logic . . . . . ТТЛ
UJT. . . . . однопереходной транзистор, двухбазовый диод
Z-Di . . . . . стабилитрон (диод Зенера)
Z-IC . . . . . стабилизатор наряжения в интегральном исполнении
...+Di. . . . . элемент со встроенным диодом
...+R . . . . . элемент со встроенным резистором
50Hz-Thy. . . . . сетевой (магистральный) тиристор
...-d. . . . . режим обеднения
...-e . . . . . режим обогащения
...d/e . . . . . режим обеднения/обогащения

Характеристики (Колонка 3)

В колонке приводятся область применения и краткие технические данные электронных полупроводниковых приборов и микросхем.

Используемые сокращения:

A. . . . . антенные широкополосные усилители
A/W-Verst . . . . . универсальный усилитель
AF output selector . . . . . переключатель выходных сигналов звука
AFC . . . . . автоматическая подстройка частоты (АПЧ)
AFT . . . . . автоматическая точная настройка
AGC. . . . . автоматическая регулировка усиления (АРУ)
ALC . . . . . автоматическая регулировка уровня сигнала
AM . . . . . амплитудная модуляция
Amp . . . . . усилитель
Amplitude limited (Antitop) . . . . . амплитудный ограничитель

APC ..... автоматическая подстройка фазы (АПФ)
ARI ..... системы коммутации
Array ..... матрица, элементы в одном корпусе
Asym ..... асимметричный
B ..... коэффициент усиления по току
Band-s ..... радиочастотный переключатель диапазона
Bi-direktional ..... двунаправленный
Blanker ..... схема гашения, схема запирания
Br ..... мост
Btx ..... телетекст
CATV ..... кабельное телевидение
CB ..... полоса частот, отведенная для служебной радиосвязи
Chopper ..... прерыватель
Chroma ..... цветность, насыщенность
Cloche filter ..... фильтр «клеш»
Coincidence detector ..... детектор совпадений
CRT ..... электронно-лучевая трубка
CTV ..... цветное телевидение
Current sourse ..... источник тока
Deflaction coil ..... отклоняющая катушка
Delay Line ..... линия задержки
Delay ..... схема задержки
Dem ..... демодуляторные каскады
Diskr ..... дискриминаторы
Divider ..... делитель
Dual ..... двойной (пара элементов в одном корпусе)
E ..... выходные каскады
East-west geometry ..... схема коррекции запад-восток
Eff ..... эффективное значение
Equal ..... эквалайзер
F/V-Convertor ..... преобразователь частота/напряжение
FB ..... дистанционное управление
FED ..... полевой диод
FM ..... частотная модуляция
Frequency detector ..... частотный детектор
Geometry processor ..... схема коррекции геометрических искажений
Gep ..... согласованные
GL ..... выпрямитель
Gunn-Di ..... диод Ганна
HF ..... высокая частота
Hi-beta ..... с большим коэффициентом усиления по току
Hi-current ..... с большим выходным током

Hi-def ..... с большой четкостью изображения
Hi-ohm ..... высокоомные
Hi-power ..... с большой выходной мощностью
Hi-prec ..... высокоточные
Hi-rel ..... высоконадежные
Hi-res ..... с высоким разрешением
Hi-speed ..... быстродействующие
Hi-volt ..... высоковольтные
Hole detector ..... детектор захвата
Horiz ..... горизонтальный (строчный)
Horizontal oscillator ..... задающий генератор строчной развертки
Horizontal pulse generaror ..... генератор импульсов запуска строчной развертки
Horizontal sync separator ..... схема выделения строчных импульсов
Hue ..... цветовой тон
HV ..... высоковольтный
Ib ..... ток базы
IF ..... промежуточная частота
Igt ..... импульсный ток
Ih ..... ток удержания
Improvement processor ..... схема улучшения качества изображения
Indic ..... индикатор
IR ..... инфракрасное излучение
Is ..... ток переключения
Iso ..... ток утечки
Ivpath-Di ..... лавинный диод
Ip ..... пиковый ток
Kl ..... ТВ, демпферный диод
KV-GL ..... высоковольтные цепи (выпрямитель)
L ..... мощные каскады
LCD ..... жидкокристаллический индикатор
LED ..... светоизлучающий диод
Limiter ..... ограничитель
Lo-noise ..... малошумящие
Lo-power ..... малой мощности
Lo-Sat ..... с низким напряжением насыщения
Lo-volt ..... низковольтные
Luminance ..... яркость
Logl ..... низкий логический уровень
M ..... смесительные каскады
Min ..... минимальные значения
Mix ..... смеситель
Mixer ..... смеситель

Mot. Tr ..... схемы управления моторами
Muting stage ..... каскад сигнала блокировки
n-ohm ..... низкоимпедансные цепи
Noise detector ..... детектор шума
Noise inverter ..... инвертор шума
O ..... генераторные каскады
OP-Amp ..... операционный усилитель
Osc ..... генератор
Oscillator frequensy adjustment .. схема подстройки частоты
Output stag for vertical sync ..... выходной каскад кадровых синхроимпульсов
Par ..... параллельно
PEP ..... пиковое значение мощности огибающей
Phase compensation ..... схема фазовой компенсации
Phase detector ..... фазовый детектор
PLL ..... фазовая автоподстройка частоты (ФАПЧ)
PQ ..... выходная мощность транзистора (передатчика)
Progr ..... программируемый
Protection circuit (Guard cirwit) .. схема защиты
PS ..... источник питания
Pulse width modulator ..... ШИМ
PWM ..... широтно-импульсная модуляция
Quadrature detector ..... квадратурный детектор
ra ..... малошумящие
Reg ..... стабилизатор, регулятор
S ..... переключающие каскады
Sawtooth generator ..... генератор пилообразных импульсов
Schottky ..... эффект Шоттки
Ser ..... последовательный
Short circuit protection ..... защита от КЗ
SMD ..... прибор для поверхностного монтажа
SMPS ..... импульсный источник питания
SS ..... быстропереключающие схемы
ss ..... пиковая максимальная величина
SSB ..... с одной боковой полосой
Stack ..... выпрямительные столбы
Sym ..... симметричные
TAZ ..... демпферный диод
tgg ..... разовый сброс
Thy-Br ..... тиристор мостовой конфигурации
Timing ..... схема синхронизации
Ton ..... звуковой канал (телевидение)
Tr ..... задающие каскады

Trap ..... режекторный фильтр
Trigger-Di ..... четырехслойный триггер-диод асимметричный
tuning ..... радиочастотный перестраиваемый
Tunnel-Di..... туннельный диод
TV transmitter identification ..... схема идентификации видеосигнала
TV..... телевидение
TV-HA..... ТВ-каскады строчной развертки
TV-VA ..... ТВ-каскады кадровой развертки
UART..... универсальный асинхронный приемопередатчик
Ub..... напряжение базы
Ucc ..... напряжение питания
UHF ..... дециметровый диапазон
Uni ..... универсальный
US..... ультразвук
USART ..... универсальный синхронно-асинхронный приемопередатчик
V..... каскады предварительного входа
V/F-convertor ..... преобразователь напряжение/частота
VC..... видеомагнитофон
Vd ..... выходные видеокаскады
Vertic ..... вертикальный, кадровый
Vertical blanking..... формирователь кадровых гасящих импульсов
Vertical geometry ..... схема коррекции по вертикали
Vertical sync separator..... схема выделения кадровых импульсов
VHF ..... диапазон метровых волн
Video amplifiee..... видеоусилитель
Voltage Limiter ..... схема ограничения напряжения
Vtx ..... телетекст
W..... коррекция цвета
X-Ray-prot..... защищенный от рентгеновского излучения
(Ta=...)..... температура окружающей среды
(Tc=...)..... температура корпуса
=(Typ)..... соответствует типу, но отличается по параметрам
-/...V ..... при известном значении коллектор-эмиттер, но других значениях параметров
...ns ..... время восстановления (диоды)
.../-ns ..... время включения (транзисторы)
../.ns..... время переключения (транзисторы)
...ms..... время выключения (тиристоры)
...+Diac ..... с интегрированным элементом
VLF ..... диапазон частот 3...30 кГц (ОНЧ)
LF..... диапазон частот 30...300 кГц (НЧ)

MF ..... диапазон частот 300...3000 кГц (СЧ)
HF..... диапазон частот 3...30 МГц (ВЧ)
VHF ..... диапазон частот 30...300 МГц (ОВЧ)
UHF..... диапазон частот 300...3000 МГц (УВЧ)
SHF ..... диапазон частот 3...30 ГГц (СВЧ)
EHF ..... диапазон частот 30...300 ГГц (КВЧ)

Корпус (Колонка 4)

В колонке приведены номера рисунков корпусов полупроводниковых приборов. Маленькая буква после номера рисунка обозначает вариант расположения выводов для полупроводниковых приборов различных классов. Эти варианты приведены в таблицах pin кодов (стр. 14), где даны условные обозначения выводов. Например, для транзисторов вариант b дает: 1 вывод — эмиттер (E), 2 вывод — коллектор (C), 3 вывод — база (B).

Производитель (Колонка 5)

В колонке даны сокращенные названия фирм-производителей. Полные названия производителей помещены на стр. 15.

Аналоги (Колонка 6)

В колонке приводятся аналоги электронных полупроводниковых приборов, наиболее близкие по своим характеристикам к исходному типу. Приведенные аналоги не исключают возможности альтернативного поиска замены, а лишь носят рекомендательный характер. Решение о замене остается за пользователем и определяется конкретными условиями. Полупроводниковые приборы, имеющие неполное соответствие, заключены в скобки с индексом ()**, где индекс обозначает:

1..... с интегрированным демпферным диодом
2..... с демпферным диодом между эмиттером и коллектором
3..... с неизолированным корпусом
4..... с различием в корпусах
5..... отличия в выводах
6..... альтернативных типов намного больше
7..... альтернативные типы с более низкими максимальными параметрами
8..... с более низкими граничными частотами
9..... с наличием других вентилей
10..... несовместимы по выводам или другое их расположение
11..... с различием в корпусах
12..... с температурными различиями
13..... с меньшим коэффициентом усиления по току
14..... отличие в параметрах
15..... с демпферным диодом и с отличием по выводам
16..... с ограниченным диапазоном температур
17..... с более высоким напряжением насыщения
18..... с подбором внешних резисторов
+ ..... множество дополнительных вариантов замены

ТАБЛИЦЫ PIN-КОДОВ

C..... Коллектор
E..... Эмиттер
B..... База
A..... Анод
K..... Катод
G..... Управляющий электрод

D..... Сток (Drain)
S..... Исток (Sourse)
G..... Затвор (Gate)
B..... Подложка (Substrate)
K..... Корпус (Case)
Sub..... Substrate — Вывод может быть использован затвором
Geh..... Паять к поверхности

• ..... Двойной
* ..... Четыре вывода
** ..... Иногда без второго вывода

Полевые транзисторы				
	1	2	3	4
a	S	G	D	
b	S	D	G	
c	G	D	S	
d	G	S	D	
e	D	G	S	
f	D	S	G	
g	G1	G2	D	S
h	D	G2	G1	S
j	S	D	G	D
k	S	D	G	Sub
l	S	D	G2	G1
m	D	S	G	Sub
n	S	G	D	Sub
o	S	G1	D	G2
p	G	D	S	D

Однопереходный транзистор				
	1	2	3	4
a	B1		B2	E
b	B2	E	B1	
c	B1	E	B2	
d	B1	B2	E	
e	E	B1		B2
f	E	B1	B2	
g	E	B2	B1	
h	B2	B1	E	
j				
k				
l				
m				
n				
o				
p				

Транзисторы + дарлингтон				
	1	2	3	4
a	E	B	C	
b	E	C	B	
c	B	C	E	
d	B	E	C	
e	C	B	E	
f	C	E	B	
g	E	B	C	Geh
h	E	C	B	C
j	B	C	E	C
k	B	E	C	Geh
l				
m	E	B	C	C
n	C	B	E	C
o	C	B	E	B
p	E	B	C	B
q	B	E	C	E
r	E	C	E	B
s	E	B	E	C
t	B	E	B	C
u	C	E	B	E
v	B	C	B	E

Тиристор, симистор, тетрод				
	1	2	3	4
a	K	G	A	
b	K	A	G	
c	G	A	K	
d	A	K	G	
e	K	A	G	A
f	G	(A)**	K	A
g	K	Gk	Ga	A
h	K	Gk	A	Ga
j	A1	A2	G	A2
k	K		G	A
l	A1	A2	G	
m	A1	G	A2	
n	A	G	K	
o	K	G	A	A
p	A2	G	A1	
q	A1	G	A2	A2
r	A	K	G	A
s	K	Ga	Gk	A
t	G	K	A	
u	K		A	G
v	G	A1	A2	

Диод				
	1	2	3	4
a	A	K		
b	K	A		
c	A		K	(K)*
d	K		A	(A)*
e	A2	K	A1	
f	A(1)	A(2)	K	
g	A	K(1)	K(2)	
h	K(1)	A	K(2)	
j	A(1)	K	A(2)	
k	K		A	K
l	A2	A1		
m	A		K	A
n	K(1)	K(2)	A	
o				
p		A	K	
q		K	A	
r	A1	A2/K1	K2	
s	A1	K2	A2/K1	
t	K1	A2	A1/K2	
u	K1	A1/K2	A2	
v				

Список производителей электронных приборов, приведенных в справочнике

dv ..... Ad anced Research Association
Aeg ..... Temic Telefunken
Alp ..... Alpha industries Inc.
Amc ..... Ampower Semicon Corp.
Amp..... Ampower Semicon Corp.
Bbc ..... BBC Brown Bo ery Ltd
Ben ..... Bendix Semicon. Products
Bog ..... Bogue Electric Manufacturing
Cbs ..... Cbs Electronics
Cen ..... Harris (GE) Transistor
Cl ..... Cle ite Tpansistor
Cod..... CODI Corp.
Cri..... Crimson Semicon. Inc.
Csr..... Csr Industries Inc.
Ctr..... Acrian Inc.
Del ..... Delco Electronics
Dio ..... Dionics Inc.
Edl ..... EDAL Industries
Etc..... Electronic Transistor Corporation
EUR..... Европейские производители
Fag ..... Fagor Electrotecnica S. Corp.
Fch ..... Fairchild Simicon.
Fer..... Ferranti Gmbh
Fjd..... Fuji Denki Seizo Com.
Fsem..... Semitronics Corporation
Fui..... Fujitsu
Gdc..... General Diode Corp.
Gen..... Harris (General Electric Semicon)
Gie ..... General Instrument
Gpd..... Germanium Power De ices Cor.
Gsi..... General Semicon. Industries Inc.
Hew ..... Hewlett Packard
Hfo ..... Halbleiterwerk Frankfurt
Hit..... Hitachi
Hug..... Hughes Aircraft Company
Idc..... International Diode Corporation
Idi ..... International De ices Inc.
Inr..... International Rectifier Corp.
Itt ..... ITT
Jap..... Японские производители
Kem ..... Kemtron Electron Product
Khe..... KH-Electronics
Kmc ..... KMC-Semicon.
Ksw..... KSW Electronics Cor.
Mal..... Mallory Distributor Product Co
Mat..... Matsushita
Mdc..... Microwa e Diode Corp.
Mic ..... Micro Electronic
Mit ..... Mitsubishi
Mi ..... Microwa e Associates
Mot..... Motorola
Msc..... Microsemicon Cor.
Mws ..... Microwa e Semicon. Corp.
Nae..... NAE INC
Nec..... NEC
Nip ..... О производителе нет данных
Njr..... New Japan Radio Co Ltd
Nsc ..... National Semicon
Nth ..... Herman Khler Electric Gmbh&Co
Oki ..... OKI Semicon
old..... О производителе нет данных, приборы сняты с производства
Org ..... Original Electronic Co Ltd
Pai..... Parametric Ind. Inc.
Phc ..... Philco Corp.
Ppc ..... PPC Products Corp.
Ray ..... Raytheon Halbleiter Gmbh
Rca ..... RCA
Rhm ..... ROHM
Sak ..... Sanken Electric Co Ltd
Say ..... Sanyo
Sca ..... Semicoa
Scn ..... Semicon Components inc.
Sem..... Semitronics Corp.
Sgs..... SGS-Thomson
Shi..... Shindengen Electronic Co Ltd
Sie..... Siemens AG
Six..... Siliconics GmbH
Sol..... Solitron De ices Inc.
Son ..... Sony
Spe ..... Space Power Electronic Inc.
Spr..... Sprague Electric
Ssc..... SSC Silec - Semi - Conductors
Ssi..... Solid State De ices
Stc..... Silicon Transistor Corp.
Stl ..... Stanley Electric Co
Sty..... О производителе нет данных
Syl..... Syl ania Semicon
Sym..... Symbol Semicon
Tag ..... TAG Semicon
TDY .... TELEDYNE Components
Tho..... Thomson
Tis..... Texas Instruments
Tix..... Texas Instruments
Tos ..... Toshiba
Tra ..... Transitron Electronic Corp.
Trw..... TRW Vertiebs CmbH
Tsc..... Teledyne Semicon.
Tun..... Tung-Sol Electric
Uni ..... Unitrode Corporation
Unz..... Unizon
Upi ..... UPI Semicon
USA ..... Ðàçëè÷íûå ïðîèçâîäèòåëè ÑØÀ
Usr ..... /o Electronzagranposta ka
Wes..... Western Electric Co
Whs..... Westinghouse Electric Cor

Промышленные стандарты и системы обозначения

Стандарт США EIA-JEDEC — Electronic Industries Accosiation

Согласно этого стандарта электронные полупроводниковые приборы обозначаются кодом (маркировкой), в котором *первая цифра* соответствует количеству p-n переходов:

1. . . . . диоды
2. . . . . транзисторы
3. . . . . тиристоры

За цифрой следует буква N и серийный номер прибора.

Японский стандарт JIS

Японский промышленный стандарт создан на базе систем JEDEC и Pro-Etectron. Согласно этого стандарта условное обозначение электронного полупроводникового прибора состоит из четырех элементов.

I-й элемент:

0. . . . . фотодиод, фототранзистор
1. . . . . диод
2. . . . . транзистор
3. . . . . четырехслойный прибор

II-й элемент указывает на принадлежность к классу электронных полупроводниковых приборов и обозначается буквой S.

III-й элемент:

A . . . . транзистор p-n-p ВЧ
B . . . . транзистор p-n-p НЧ
C . . . . транзистор n-p-n ВЧ
D . . . . транзистор n-p-n НЧ
E . . . . диод Есаки
F . . . . тиристор
G . . . . диод Гана
H . . . . однопереходной транзистор
J . . . . . полевой транзистор с *p* каналом
K . . . . полевой транзистор с *n* каналом
M . . . . симметричный тиристор
R . . . . выпрямительный диод
S . . . . малосигнальный диод
T . . . . лавинный диод
V . . . . *pin* диод
Z . . . . . стабилитрон

IV-й элемент — серийный номер.

Европейская система PRO ELECTRON – International Pro Electron

Европейская система PRO ELECTRON — International Pro Electron. Согласно этой системы электронные полупроводниковые приборы обозначаются:

Первая буква — материал, из которого изготовлен прибор:

A . . . . германий

B . . . . кремний

C . . . . арсенид галлия

R . . . . хим. соединение (например, сульфид кадмия)

Вторая буква соответствует подклассу прибора и указывает на его функциональное назначение:

A . . . . диоды в цепях сигнала, маломощные

B . . . . варикапы

C . . . . транзисторы низкочастотные, маломощные

D . . . . транзисторы низкочастотные, мощные

E . . . . диоды туннельные

F . . . . транзисторы высокочастотные

G . . . . многоэлементные, многофункциональные приборы со специальной третьей буквой

H . . . . магнитодиоды

L . . . . транзисторы высокочастотные, мощные

N . . . . оптопары

P . . . . фототранзисторы (возможен вариант третьей буквы)

Q . . . . светоизлучающие приборы: светодиоды, лазерные диоды (возможен вариант третьей буквы)

R . . . . тиристоры маломощные (возможен вариант третьей буквы)

S . . . . транзисторы маломощные, переключающие

T . . . . тиристоры мощные (возможен вариант третьей буквы)

U . . . . транзисторы, мощные переключатели

W . . . . приборы на поверхностных акустических волнах

X . . . . варакторы, умножители, диоды с накоплением заряда

Y . . . . диоды выпрямительные

Z . . . . стабилитроны, опорные диоды, диоды специального назначения (возможен вариант третьей буквы)

Номер серии/специальная третья буква

Номер серии состоит из трехзначного числа, начиная от 100 до 999, для электронных полупроводниковых приборов общего применения, либо специальной буквы (Z, Y, X и т.д.) и двухзначного числа, начиная с 10 до 99, для ЭПП, применяемых в промышленном оборудовании или специального назначения. Специальная третья буква не имеет фиксированного значения, кроме случаев:

A . . . . для симисторов после второй буквы «R» или «T»

F . . . . для излучающих и принимающих приборов в системах опто-волоконной связи после второй буквы «G» или «P», или «Q». Если вторая буква «G», то первая буква указывает материал, из которого изготовлен основной оптический прибор

L . . . . для полупроводниковых лазеров, не используемых в системах оптоволо-

конной связи, после второй буквы «G» либо «Q»

O . . . . для оптосимисторов, после второй буквы «R»

T . . . . для двухцветных светодиодов, после второй буквы «Q»

W. . . . для диодов специального назначения, после второй буквы «Z»

Пример:

AA112 . . . германиевый маломощный диод общего применения

BD232. . . . кремниевый мощный низкочастотный транзистор общего применения

CQY17 . . . арсенид-галлиевый светоизлучающий диод для промышленного оборудования

Версия

Одна или две буквы могут дополнить основное обозначение ЭПП, показывая отличие в электрических параметрах либо отличие в корпусе от базового варианта. Эти буквы не имеют фиксированных значений, кроме букв «R» — обратная полярность, «W» — SMD.

Суффикс

Суффикс отделен от обозначения ЭПП дефисом. Для стабилитронов суффикс указывает отклонения от указанного напряжения стабилизации в процентах:

A — 1%

B — 2%

F — 3%

C — 5%

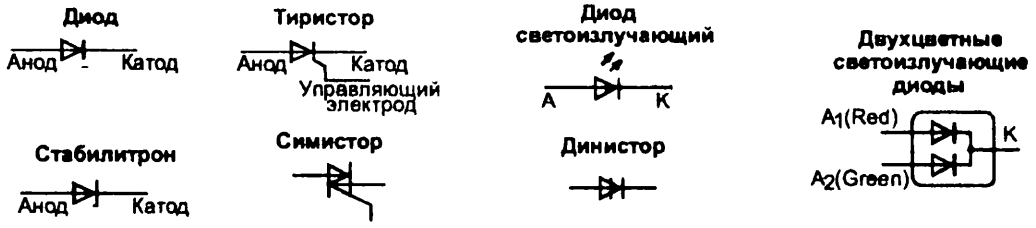
D — 10%

E — 20%

Например: BZY74-C6V3 — напряжение стабилизации 6,3 В ±5% (десятичная запятая заменяется буквой V). Значения суффикса для других подклассов промышленных электронных полупроводниковых приборов и ЭПП специального назначения здесь опускаются.

Графические обозначения электронных полупроводниковых приборов

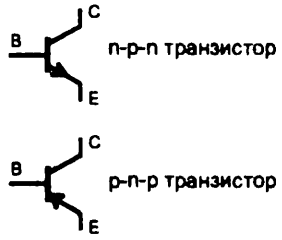
ДИОДЫ, ТИРИСТОРЫ

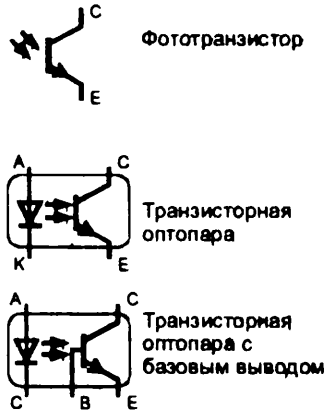


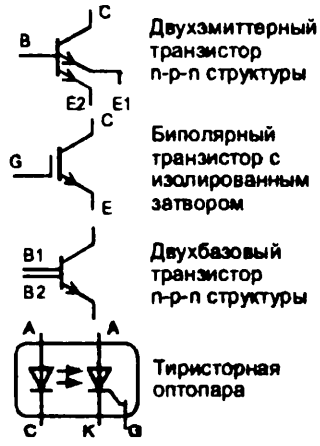
ТРАНЗИСТОРЫ БИПОЛЯРНЫЕ

C ..... коллектор
E ..... эмиттер
B ..... база
BS ..... база S

A ..... анод
C ..... катод
G ..... управляющий электрод







ТРАНЗИСТОРЫ ПОЛЕВЫЕ

D ..... сток (Drain)
S ..... исток (Sourse)
G ..... затвор (Gate)
B ..... подложка (Substrate)
C ..... корпус (Case)





Important Notes on Use

In the following table section the most important semiconductor components – irrelevant as to whether it is dealing with transistors, diodes, thyristors integrated circuits etc. – are listed in strict alphabetical order. The individual types are provided with the most important relevant short data, and – as far as possible and as far as purposeful – suitable comparative types are named. This table is supplemented and extended with every new edition. Old types are **never** cancelled. Old tables should therefore always be removed (there is absolutely no risk of information loss) thus preventing valuable time being spent on searching through stacks of tables.

Column 1 ("Type")

The type designations correspond to those of the respective manufacturer documentations. They are sometimes stamped on the components themselves in a deviating or abbreviated form.

With several identical type designations of one kind or component (e. g. "BF 232") the abbreviation of the manufacturer is added in square brackets "[...]" to the type designation.

Selection identifications through added on letters or figures are only then considered if this is important in practice and with type comparison.

Column 2 ("Device")

Short definition of the semiconductor component.

Used abbreviations:

A/D-IC	Analog-to-digital converter
BiMOS-IC	Integrated circuit (Bipolar, + MOS technology)
CCD-IC	Charge-coupled device
CMOS-Logic	Digital-logic circuit (CMOS technology)
C-Di	Capacitance diode (Varactor, varicap)
Diac	3-layer-trigger diode, symmetrical
DIG-IC	Digital integrated circuit
dRAM-IC	Read-write memory, dynamic
D/A-IC	Digital-to-analog converter
EAROM-IC	Memory, nonvolatile, alterable
ECL-Logic	Emitter-coupled logic
EEPROM-IC	Memory, nonvolatile, electrically erasable
EPROM-IC	Memory, nonvolatile, UV-erasable
FPLA	= PAL, field programmable
F-Thy	Fast thyristor
GaAs	Gallium arsenide
Ge-Di	Germanium diode
Ge-N	Germanium NPN transistor
Ge-P	Germanium PNP transistor
GTO-Thy	Gate turn off thyristor
Hybrid-IC	Integrated circuit (hybrid technology)
IC	Integrated circuit
I/O-IC	Input/output IC for microcomputer
KOP-IC	Comparator (operational amplifier)
LIN-IC	Linear integrated circuit
MOS-...*	With integrated gate protection diode
MOS-FET-d	Metal oxide FET, depletion type
MOS-FET-e	Metal oxide FET, enhancement type
MOS-IC	Integrated circuit (MOS technology)
MOS-N/P-IGBT	Iso-gate bipolar transistor
NMOS-IC	N-channel MOS-IC
N-FET	N-channel field-effect transistor
Opto	Optoelectronic component
OP-IC	Operational amplifier
PAL-IC	Programmable logic array
PIN-Di	PIN diode
PMOS-IC	P-channel MOS-IC
PROM-IC	Electrically programmable ROM
PUT	Programmable Unijunction transistor (UJT)
P-FET	P-channel field-effect transistor
Ref-Di	Reference diode (highly stable Z-diode)
ROM-IC	Read-only memory
SAS	Silicon asymmetrical switch
SBS	Silicon bilateral switch
Se-Di	Selenium diode
Si-Br	Silicon bridge rectifier
Si-Di	Silicon diode
Si-N	Silicon NPN transistor
Si-N-Darl	Silicon NPN Darlington transistor
Si-P	Silicon PNP transistor
Si-P-Darl	Silicon PNP Darlington transistor
Si-St	Silicon-stabi-diode (operation in forward direction)
sRAM-IC	Read-write memory, static
SUS	Silicon unilateral switch
Tetrode	P- + N-gate thyristor
Thermistor	Temperature depending resistor
Thy	Thyristor
Thy-Br	Thyristor bridge configuration
Triac	Full-wave thyristor
Trigger-Di	4-layer trigger diode, asymmetrical
TTL-IC	Linear integrated circuit (TTL technology)
TTL-Logic	Digital logic circuit (transistor - transistor logic)
UJT	Unijunction transistor
Varistor	Voltage depending resistor (VDR)
Z-DI	Z-diode (operation in reverse direction)
Z-IC	Voltage regulator, voltage stabilizer
...+Di	With integrated damper diode
...+R	With integrated resistors
50Hz-Thy	Thyristor for mains operation
µC-IC	Single-chip microcomputer (MOS)
µP-IC	Microprocessor, CPU (MOS)

Column 3 ("Short description")

Short data or description of function of each type.

Used abbreviations:

A	Antenna and wideband amplifiers (CATV)
AFC	Automatic frequency control
AFT	Automatic fine tuning
AGC	Automatic gain control
ALC	Automatic level control
AM	RF application (AM range)
APC	Automatic phase control
ARI	Traffic information system (West Germany)
Array	Arrangement of numerous elements in a single case
asym	Asymmetrical
AV	Audio/Video
A/W-Verst	Record/playback amplifier
B	DC forward current gain
Backward	Backward diode
Band-S	RF band switching
bidirektional	Bidirectional diode
Br	Bridge rectifier
Btx	Interactive video text
Camera	Video camera
CATV	Broad band cable amplifier
CB	CB-radio
CD	CD-player
Chopper	Chopper
contr. av.	Controlled avalanche
CPU	Central processing unit
CRT	Cathode ray tube
CTV	Color TV
Dem	Demodulator

Diskr	Discriminator
DMA	Direct memory access controller
Dual	Dual transistors for differential amplifiers or dual diode
E	Output stages
Equal	Equalizer
ESD	Electrostatic discharge
FB	Remote control
FED	Field effect diode
FIFO-IC	First-in First-out memory
FLT	Fluorescent tubes
FM	RF application (FM range)
FREDFET	V-MOS-FET with fast parasitic diode
F/V-Converter	Converter frequency to voltage
gep	Matched types
GI	Rectifier (general)
Gunn-Di	Gunn diode
HA	TV horizontal deflection stages
HF	RF application (general)
hi-beta	High current gain
hi-current	For high output current
hi-def	High definition
hi-power	High output power
hi-prec	High precision
hi-rel	High reliability
hi-res	High resolution
hi-speed	High speed
hi-volt	For high voltages
Horiz.	Horizontal
h-ohm	For high impedance demodulator circuits
Ib	Break-over current
Igt	Gate trigger current
Ih	Holding current
Impatt-Di	Impatt diode
Indic.	Indicator
IR	Infra-red
Ip	Peak point current
IPD	Intelligent power device
Is	Switching current
Iso	Insulated
Itsm	Surge current
Iv	Valley point current
kV-GI	High voltage rectifier
L	Power stages
LCD	Liquid crystal display
LED	Light-emitting diode
LIFO-IC	Last-in first-out memory
Limiter	Limiter
lo-drive	Low drive power required
lo-drop	Low voltage drop
LogL	Logic Level (U_{th} ≈ 0,8...2V)
lo-power	Low power consumption
lo-sat	Low collector - emitter saturation voltage
lo-volt	For low voltages
M	Mixer stages
Min	Miniaturized
MMU	Memory management unit
Multipl	Frequency multiplier
NF	AF applications
Nix	Nixie driver (digital display tubes)
Noise suppr.	Noise suppression
n-ohm	For low impedance demodulator circuits
O	Oscillator stages
OFW/SAW-Filter	Surface acoustic wave filter
OP-Amp.	Operational amplifier
OSD	On-screen display
par	Parallel
PEP	Peak envelope power
PIP	Picture-in-picture
PLL	Phase-locked loop
PQ	RF-output power (transmitter transistor)
progr	Programmable
PS	Power supply
PWM	Pulse-width modulation
ra	Low noise
RadH	Designed for space aviation use (radiation hardened)
re	AGC stages
Recorder	Tape and cassette recorder
Reg	Regulator
S	Switching stages
Schottky	Schottky diode
ser	Serial
SHF	RF applications (>5 GHz)
SMD	Surface mounted device
SMPS, SN	Switch-mode power supplies
SS	Fast switching stages
SSB	Single sideband operation
stack	Rectifier stacks
sym	Symmetrical types
TAZ	Suppressor diode
tgq	Reset-time
Thy-Br	Thyristor bridge configuration
Thy-Modul	Arrangement of numerous thyristors in a single case
Ton	TV sound channel
Tr	Driver stages
Trigger-Di	4-layer trigger diode, asymmetrical
Tuning	RF tuning diode
Tunnel-Di	Tunnel diode
TV	Television applications
UART	Universal asynchronous receiver/transmitter
Ub	Break over voltage
Ucc, Us	Supply voltage
UHF	RF applications (>250 MHz)
Uni	General purpose types
US	Ultrasonics
USART	Universal synchronous/ asynchronous receiver/transmitter
V	Pre/input stages
VA	TV vertical deflection types
VC	Video recorder
Vertik.	Vertical
VHF	RF applications (approx. 100...250MHz)
Vid	Video output stages
VIR	NTSC color correction
Vtx	Video text, teletext
V/F-Converter	Converter voltage to frequency
X-Ray-prot.	X-ray protection
ZF	IF stages
ZV	Integrated trigger amplification (Darlistor)
ß	Short-circuit current gain at 1 kHz
(eff)	r.m.s. value
(ss)	Peak value
(Ta = ...°)	Ambient temperature if not 25°C
(Tc =...°)	Case reference temperature if not 25°C (power types)
= [Typ]:	Identical with [type], however: [data, case, Pin-Code, etc.]
→	See under
-/...V	Only U_{CE0} known; otherwise always U_{CB0} or U_{CB0}/U_{CE0} (transistors)
...ns	Reverse recovery time (diodes)
.../-ns	Turn-on time (transistors)
.../...ns	Turn-on/turn-off time (transistors)
...µs	Circuit commutated turn-off time tq (thyristor)
... + Diac	With integrated diac
µComp	Microcomputer
≈ [Typ]	Similar to the named type (description see there)

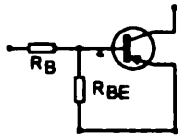
Column 4 ("Fig.")
Related drawing number (figure) and pin assignment (appended letter) with discrete semiconductors. In the pin assignment table, the associated column ("Transistor", "FET", "Thyristor", "Diode", "Z-IC") must be observed. With ICs just a schematic drawing is provided without pin assignment. All drawings are situated at the end of the table. The degrees mark (°) means: case with additional heat sirik.

Column 5 ("Manufacturer")
The names of the manufacturers are abbreviated to save space. The complete name of each manufacturer is listed alphabetically on page XXII. We cannot vouch for completeness and availability.
If a number of manufacturers are named for a single type, data is given of only one, due to the data of a single type differing from one manufacturer to another slightly under unlike measurement conditions.

Column 6 ("Comparison types")
With the details on the alternate types, just a selection of the types "closely related" to the original type is given. They are preferably types which are not too difficult to obtain.
In practice there are usually many more alternate types applicable than there is room for in this table. The characterizing mark "+ +" after the last alternate type is to attract particular attention.
The "Selector tables" in the ECA data bases under **http://www.ecadata.de/search/**, on CD-ROM or as books conceal unsuspected furthering possibilities. These ECA data books should by all means be consulted for an exact type comparison in critical cases.
If not otherwise mentioned in footnotes, the given alternate types have the same or better electrical data and can be applied without mechanical problems.
The same pin assignment has only been given attention to in the case of power types and ICs, as with small components the connections can be easily exchanged to fit. A check on any differing assignments is very much advised, and with this table is easy to carry out.
When a comparison type is followed by a maker's name (abbreviated) in square brackets, this means the data stems from this manufacturer and has not been verified by the author.
In order not to exceed the capacity of this table, the detailed ECA data bases online or on CD-ROM have partly had to be referred to. The incredible variety of the components and comparison possibilities cannot be fully shown in this scope with digital logic circuits, voltage stabilizers, Z-diodes, thyristors and operational amplifiers.

Footnote list on the comparison type
with comparison types in brackets ( ):

1 with integrated damper diode
2 damper diode between emitter and collector necessary externally
3 not insulated case
4 different case - possibly mechanical adaption necessary
5 the differing pin assignment possibly requires different assembly
6 alternate type is a little larger or with a different pin-spacing
7 alternate type with lower maximum ratings
8 lower transition frequency (f_T)
9 also with other gate trigger current
10 alternate IC is not pin-compatible or with a different pin-spacing
11 also with other gate trigger current and the alternate type is with different case
13 lower forward current gain (B, h_{FE}, ß, h_{fe})
15 No. 1 + 5
16 equivalent type with limited temperature range
17 higher saturation voltage (U_{CESat})
18 suitable resistor required externally



+ + Many further comparison possibilities

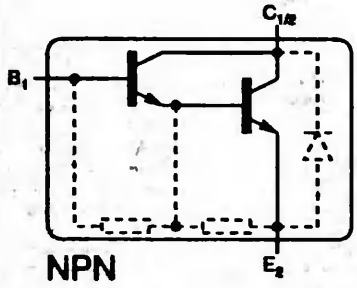
Column 7 ("ECA Infos")
Further informations about this type like particularized data (data), original data sheets (pdf) or pinout (pinout) you will find in the ECA online data base under **http://www.ecadata.de/search/.**
Please visit also our main page site **http://www.eca.de** for additional informations about our online data base.
In all critical application cases the relevant parameters of the comparison types are to be compared with those of the original in order to prevent any "surprises"!
Despite very careful research, errors excepted. There is no liability for failure in practice.

ABBREVIATIONS OF MANUFACTURERS

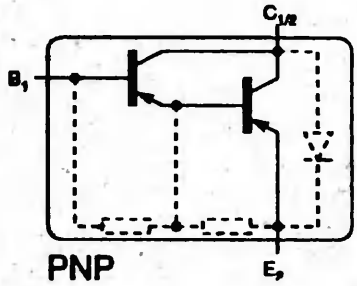
++	More additional producer	
Acc	Accordion Electric Ltd. Co.	
Adv	Advanced Research Association	
Aeg	TEMIC TELEFUNKEN microelectronic	www.temic.de
Aei	AEI Semiconductors, Ltd.	
Akm	Asahi Kasei Microsystems	www.akm.com
Ald	Advanced Linear Devices Inc.	www.aldinc.com
Alp	Alpha Industries, Inc.	www.alphaind.com
Amc	Ampower Semiconductor Corp.	
Amd	Advanced Micro Devices GmbH	www.amd.com
Amd	Advanced Micro Devices Inc.	www.amd.com
Ame	Aksjeselskapet Mikro-Elektronik	
Amf	American Machine & Foundry	
Amp	Amperex Electronic Corp.	
Ams	American Microsystems, Inc.	www.amis.com
Anc	Ancom, Ishikawa Sangyo Ltd. Co.	
And	Analog Devices	www.analog.com
Ane	Analog Systems	
Apt	Advanced Power Technology	www.advancedpower.com
Apx	Apex Microtechnology Corp.	www.apexmicrotech.com
Atm	Atmel	www.atmel.com
Ava	Avantek, Inc.	
B&h	Bell & Howell Columbia Trading Ltd. Co.	
Bbc	BBC Brown Bovery, Ltd.	
Bec	Beckmann Instruments Inc.	
Bel	Bentron Elektronik GmbH	
Ben	Bendix Semiconductor Products	
Bog	Bogue Electric Manufacturing	
Bra	Bradley Semiconductor Corp.	
Bub	Burr-Brown Research Corp.	www.burr-brown.com
Cat	Catalyst Semiconductor	www.catsemi.com
Cbs	CBS electronics	
Cdi	Continental Device India, Ltd.	www.cdil.com
Cen	Central Semiconductor Corp. Devision	www.centralsemi.com
Chy	Cherry Semiconductor Corp.	www.cherry-semi.com
Cla	Clairex Technologies Inc.	www.clairex.com
Clv	Clevite Transistor	
Cml	Computer Labs	
Cod	CODI Corporation	
Com	Cominear	
Cpc	C.P. Clare Transistor Corporation	www.cpclare.com
Cpd	Control Products Division Devar Inc.	
Crb	CR.BOX	
Crl	Crimson Semiconductor, Inc.	
Csr	CSR Industries, Inc.	
Ctr	Acrian Inc.	
Cys	Cypress Semiconductor Corp.	www.cypress.com
Dal	Dallas Semiconductor	
Dat	Datel Inc.	www.datel.com
Dat	Datel GmbH	www.datel.com
Dci	Dynamic Communications, Inc.	
Del	Delco Electronics	
Dic	Dickson Electronics Corp.	
Die	Diotec GmbH	www.diotec.com
Dio	Dionics, Inc.	
Dmc	Dynamic Measurement Corp.	
Dpm	Dense-Pac Microsystems, Inc.	www.dense-pac.com
Dsi	Discrete Semiconductors Industries	
Dtc	Diode Transistor Co., Inc.	
Ecg	ECG Philips	eu2.semiconductors.com
Edi	Electronic Designs, Inc. (EDI)	www.electronic-designs.com
Edl	EDAL Industries, Inc.	
Ely	El, Elektronskaja Industrija	
Ela	Élantec Semiconductor Inc.	www.elantec.com
Elc	Elcoma	
Ele	Electromation Co.	
Elx	Electroimpex	
Emi	Emihus Microcomponents Ltd.	
Ems	Enhanced Memory Systems Inc.	www.enhanced.com
Etc	Electronic Transistor Corporation	
EUR		
Exl	EXAR Corp.	www.exar.com
Exl	Exel Microelectronics, Inc. (Rohm Co. Ltd.)	www.rohm.com
Fag	Fagor Electrotecnica, S. Coop.	www.fagor.com
Fan	Fanon Transistor Corporation	
Fch	Fairchild Semiconductor GmbH	www.fairchildsemi.com
Fch	Fairchild Semiconductor	www.fairchildsemi.com
Fcs	Fairchild Semiconductor GmbH	www.fairchildsemi.com
Fcs	Fairchild Semiconductor	www.fairchildsemi.com
Fer	Ferranti GmbH	
Fer	Ferranti (Electronics) Semiconductors Ltd.	
Fjd	Fuji Denki Seizo Company	www.fujielectric.co.jp
Fjd	Fuji Electric GmbH	www.fujielectric.co.jp
Fjd	Fuji Semiconductor Inc.	www.fujisemiconductor.com
Fmi	FMI Inc.	
Fpm	Fine Products Microelectronics Corporation	
Ful	Fujitsu Mikroelektronik GmbH	www.fujitsu-ede.com
Ful	Fujitsu Ltd.	www.fujitsu.co.jp
Fuj	Fujitsu Ltd.	www.fujitsu.co.jp
Ful	Fujitsu Mikroelektronik GmbH	www.fujitsu-ede.com
Gdc	General Diode Corporation	
Gen	Harris (General Electric) Semiconductor	www.semi.harris.com
Gie	General Instrument	www.gi.com
Gin	General Instrument, Optoelectronic Div.	www.gi.com
Gol	Goldstar (LG Electronics Deutschland)	www.goldstar.de
Gol	Goldstar (LG Electronics Inc.)	www.lg.co.kr
Gpd	Germanium Power Devices Corporation	
Gse	General Semiconductor	www.gensemi.com
Gsl	General Semiconductor	www.gensemi.com
GUS	UdSSR States located producer	
Haf	ASEA HAFO AB	
Hal	Halex Inc.	
Ham	HAMAMATSU PHOTONICS K.K.	www.hpk.co.jp
Ham	Hamamatsu Photonics Deutschland GmbH	www.hamamatsu.de
Har	Harris Semiconductor	www.harris.com
Har	Harris Semiconductor	www.harris.com
Hbc	Hybrid Systems Corp.	
Hei	EG&G Heimann Optoelectronics GmbH	www.heimann-opto.de
Hew	Hewlett Packard	www.hp.com/hp-comp
Hew	Hewlett-Packard GmbH	www.hp.com/hp-comp
Hfo	Halbleiterwerk Frankfurt/Oder	
Hit	Hitachi Europe GmbH	www.halsp.hitachi.com
Hit	Hitachi Europe Ltd.	www.halsp.hitachi.com
Hon	Honeywell AG Optoelectronics	www.honeywell.de
Hon	Honeywell International Inc.	www.honeywell.com
Hpa	Hewlett Packard	www.hp.com/hp-comp
Hsc	Helios Semiconductor	
Hsm	HI-SINCERITY MICROELECTRONICS	www.hsmc.com.tw
Hug	Hughes Aircraft Company	
Hun	Hyundai Electronics Industries Co., Ltd.	www.hei.co.kr
Hun	Hyundai Electronics Deutschland (HED)	www.hea.com
Idc	International Diode Corporation	
Idl	International Devices, Inc.	
Idr	I.P.R.S. Baneasa	
Idt	Integrated Device Technology (IDT)	www.idt.com
Idt	Integrated Device Technology GmbH	www.idt.com
Iic	ILC Data Device Corp.	
Inf	Infineon Technologies AG (Siemens Semiconductor Group)	www.infineon.com
Inm	INMOS (siehe SGS-Thomson)	www.st.com
Inr	International Rectifier Corporation	www.irf.com
Int	Intel GmbH	www.intel.com
Int	Intel Corporation	www.intel.com
Isi	Harris Semiconductor	www.semi.harris.com
Iso	Isocom Inc. (Components, LTD.)	www.isocom.com
Iss	Integrated Silicon Solution, Inc.	www.issi.com
Ite	Intech/FMI Inc.	
Itl	Intersil Europe	www.intersil.com
Itl	Intersil Corporation Headquarters	www.intersil.com
Itr	Intronics Inc.	
Itt	ITT Intermetall (Micronas Semiconductors)	www.itt-sc.de
Ixy	IXYS Semiconductor GmbH	www.ixys.com
JAP	Unkown or several japanese Producter	
Jno	JENOPTIK Laserdiode GmbH	www.jold.de
Kec	KEC, Korea Electronics Co., Ltd.	www.kec.co.kr
Kem	Kemtron Electron Products	
Ker	Kertron, Inc.	
Khe	KH-Electronics	
Kmc	KMC-Semiconductor	
Kme	Kombinat Mikroelektronik Karl Marx Erfurt	
Ksw	KSW Electronics Corp.	
Lam	Lambda Semiconductors	
Lbd	Lambda Semiconductors	
Lic	Linear Technology Corporation	www.linear-tech.com
Lic	Linear Technology GmbH	www.linear-tech.com
Lif	Littelfuse	www.littelfuse.com
Lit	Taiwan Liton Electronic Co., Ltd.	www.liteon.com
Lrc	Leshan Radio Company Ltd.	www.lrc-china.com
Ltc	Linear Technology Corporation	www.linear-tech.com
Ltc	Linear Technology GmbH	www.linear-tech.com
Lte	Landsdale Translator & Electronics, Inc.	
Ltt	Lignes Telegraphiques et Telephoniques (SGS-Thomson)	www.st.com
Luc	Lucas Electrical Co., Ltd.	
Mal	Mallory Distributor Products Co.	
Mat	Matsushita Electronics Corp.	www.mei.co.jp
Mat	Matsushita Electronics (Europe) GmbH	www.matsushita-europe.com
Max	Maxim Integrated Products Ltd.	www.maxim-ic.com
Mbl	M.B.L.E. (Philips Semiconductors)	eu2.semiconductors.com
Mcc	Microchip Technology Inc.	www.microchip.com
Mcr	MICREL Semiconductor UK Lim.	www.micrel.com
Mdc	Microwave Diode Corp.	
Med	Meder Electronic AG	www.meder.com
Mhs	TemicTelefunken microelectronic GmbH	www.temic.de
Mic	Micro Electronics, Ltd.	
Min	Micron Technology, Inc.	
Mis	Mistral (SGS-Thomson)	www.st.com
Mit	Mitsubishi Electric Europe GmbH	www.mitsubishichips.com
Mit	Mitsubishi Electric Corporation	www.mitsubishichips.com
Miv	Microwave Associates	

Mmi	AMD (Advanced Micro Devices)	www.amd.com
Mod	Modular Devices Inc.	
Mos	Mostek (SGS-Thomson)	www.st.com
Mot	Motorola GmbH	www.mot-sps.com
Mot	Motorola Semiconductor Products Ltd.	www.mot-sps.com
Mpi	Micropac Industries Inc.	www.micropac.com
Mpi	Micropac Europe	www.micropac.com
Mps	Micro Power Systems	
Msc	Microsemi MicroPower Products	www.microsemi.com
Msp	MOSPEC SEMICONDUCTOR CORP.	www.mospec.com.tw
Msy	Microsystems	
Mts	Mitsumi Electric Co. Ltd.	www.mitsumi.com
Mul	Mullard Ltd. (Philips Semiconductors)	eu2.semiconductors.com
Mwa	Microwave Associates, Inc.	
Mws	Microwave Semiconductor Corporation	
Nac	National Aircraft Corporation	
Nae	NAE, Inc.	
Nas	North American Semiconductor Co., Inc.	
Nec	NEC Electronics (Germany) GmbH	www.nec.de
Nec	NEC Electronics Inc.,	www.ic.nec.co.jp
Neq	Nuclear Equipment Corp.	
New	Newmarket Transistors, Ltd.	
Nih	Nihon Inter Electronics Corporation	www.niec.co.jp
Njr	New Japan Radio Co., Ltd.	www.njr.com
Npp	National Power Products	
Nsc	National Semiconductor GmbH	www.national.com
Nsc	National Semiconductor	www.national.com
Nte	NTE Electronics Inc.	www.nteinc.com
Ntn	Hermann Koehler Elektrik GmbH & Co.	
Nuc	Nucleonic Products Co., Inc.	
Odc	Opto Diode Corporation	www.optodiode.com
Olz	Olzumi Seisakusho	
Old	OKI Electric Europe GmbH	www.oki.com
Old	OKI Electric Industry Co. Ltd.	www.oki.com
old	Old unknown producer	
Omr	OMRON Europe B.V. (OMCE)	www.omron.de
Ons	ON Semiconductor Inc.	www.onsemiconductor.com
Opa	Opamp Labs Inc.	
Opt	Optical Electronics Inc.	
Org	Origin Electric Co., Ltd.	
Pai	Parametric Industries, Inc.	
Pan	Panasonic	www.panasonic.co.jp
Pan	Panasonic Deutschland GmbH	www.panasonic.de
Per	Pericom Semiconductor Corporation	www.pericom.com
Phb	Philco Radio Televisao, Ltda.	
Phc	Philco Corporation	
Phl	Philips Semiconductor	eu2.semiconductors.com
Plh	Plher Semiconductors	
Pls	Plessey Semiconductors, Ltd.	
Ply	Plessey Semiconductors, Ltd.	
Pmi	Precision Monolithics Inc.	
Poi	Power Innovations Ltd.	www.powinv.com
Ppc	PPC Products Corporation	
Ptc	Power Transistor Components/Allen-Bradley	
Pti	Power Tech, Inc.	www.power-tech.com
Pwi	Power Integrations, Inc.	www.powerint.com
Pwx	Powerex Inc.	www.pwrx.com
Qdc	Quaildyne Corporation	
Qse	Quality Semiconductor Inc.	www.qualitysemi.com
Qsi	Quality Semiconductor Inc.	www.qualitysemi.com
Qtc	Quality Technologies Corporation	
Qua	Quality Technologies Corporation	
Ray	Raytheon Halbleiter GmbH	www.raytheon.com
Ray	Raytheon Semiconductor Co.	www.raytheon.com
Rca	RCA Corporation (Harris Semiconductor)	www.semi.harris.com
Rec	Rectron Semiconductor	www.rectron.net
Ren	Renesas Technology Singapore Pte. Ltd.	www.renesas.com
Rfm	RF Micro Devices, Inc.	www.rfmd.com
Rhm	Rohm Co. Ltd.	www.rohm.co.jp
Rhm	Rohm Electronics GmbH	www.rohm.com
Riz	RIZ Radio Industrie Zagreb/Iskra Ljubljana	
Roc	Rochester Electronics Inc.	www.rocelec.com
Roe	Vishay Roederstein GmbH	www.vishay.com
Roh	Rohm Electronics GmbH	www.rohm.com
Roh	Rohm Co. Ltd.	www.rohm.co.jp
Rol	Roitner-Lasertechnik	
Rtc	R.T.C. La Radiotechnique-Compelec	
Sak	Sanken Electric Co., Ltd. (Allegro Micro Systems)	www.sanken-ele.co.jp
Sam	SAMSUNG Semiconductor Europe GmbH	www.samsungsemi.com
Sam	SAMSUNG EUROPE PLC. SEMICONDUCTOR DIVISION	www.samsungsemi.com
Say	Tokyo Sanyo Electric Co., Ltd.	www.semic.sanyo.co.jp
Say	SANYO Semiconductors (Europe) GmbH	www.sanyo.de
Sca	Semicoa	
Scn	Semicon Components Inc.	www.semicon.com
Seb	Semelab	
Sem	Semitronics Corporation	
Sen	Sensitron Semiconductor	
Seq	SEEQ Technology, Inc.	www.seeq.com
Ses	Sescosem (Thomson CSF)	
Sgs	SGS-THOMSON Microelectronics GmbH	www.st.com
Sgs	SGS Semiconductor Ltd	www.st.com
Sha	Sharp Microelectronics	www.sharpmeg.com
Sha	Sharp Electronics (Europe) GmbH	www.sharp-eu.com
Shi	Shindengen Inc.	www.shindengen.com
Sie	Siemens AG	www.infineon.com
Sig	Signetics Corporation	www.signetics.com
Sil	Silonex Inc.	www.silonex.com
Sil	Silicon General Inc. (Linfinity Microelectronics)	www.linfinity.com
Sip	Sipex Corporation	www.sipex.com
Sip	SIPEX GmbH	www.sipex.com
Six	Siliconix GmbH (Temic Telefunken microelectronic GmbH)	www.siliconix.com
Skr	Semikron GmbH & Co. KG	www.semikron.de
Sld	Solid State Industries, Inc.	
Sml	Semitron, Ltd.	
Smo	Semi-Onics	
Smt	Semtech Corporation	www.semtech.com
Sol	Solitron Devices, Inc.	
Son	Sony Europa	www.sel.sony.com/semi/
Son	Sony Semiconductor Europe Limited	www.sel.sony.com/semi/
Sov	UdSSR	
Spc	Solid Power Corporation	
Spe	Space Power Electronic, Inc.	
Spr	Sprague Electric Co.	
Spt	Signal Processing Technologies	www.spt.com
Ssc	SSC, Sitec - Semi - Conductors	
Ssi	Solid State Devices, Inc.	
Sss	Solid State Scientific, Inc.	
Sta	Standard Telephones & Cables	
Stc	Silicon Transistor Corp. (STC)	
Sti	Stanley Electric GmbH	www.stanleyelec.com
Sti	Stanley Electric Co.	www.stanleyelec.com
Stm	STMicroelectronics	www.st.com
Stw	Stow Laboratories, Inc.	
Stx	Supertex Inc.	www.supertex.com
Sty	Semiconductor Technology, Inc.	
Stz	ST Semicon, Inc.	
Syl	Sylvania Semiconductors	
Sym	Symbol Semiconductor Inc.	
Tag	TAG Semiconductors	www.temic.de
Tdr	Teccor Electronics Inc.	www.teccor.com
Tcs	Telcom Semiconductor Inc. (Teledyne Components)	www.telcom-semi.com
Tdy	TELEDYNE Components	
Tei	Temic Telefunken Microelectronic GmbH	www.temic.de
Tem	Temic Telefunken Microelectronic GmbH	www.temic.de
Tes	Tesla Electronic Components (Ecimex)	
The	Theta-J Corporation	
Tho	SGS-THOMSON Mikroelektronik GmbH	www.st.com
Thr	Tree-Five System Inc.	
Tic	Transistor International Corporation	
Tix	Texas Instruments Deutschland GmbH	www.ti.com
Tix	Texas Instruments	www.ti.com
Tom	Thomson Bauelemente GmbH	www.tcs.thomson-csf.com
Tos	Toshiba Electronics Europe GmbH	www.toshiba.com
Tos	Toshiba Electronics U.K. Ltd.	www.toshiba.com
Toy	Toyo Denki Seizo Electronics Industry Corp.	
Tra	Transitron Electronic Corp.	
Trw	TRW Vertriebs GmbH	www.trw.com
Trw	TRW LSI Products Inc. (Semiconductors)	www.trw.com
Tsc	Teledyne Semiconductor	
Tsm	Tungsram GmbH	
Tun	Tung-Sol Electric	
Twa	Tokyo Wireless Appersatures	
Ucp	Unitra-Cemi (Polen)	
Unc	HI-Tech Co., Ltd (Unitra-Cemi)	www.hitech.com.pl
Ung	Ungarn	
Uni	Unitrode Corporation	www.unitrode.com
Uni	Unitrode Electronics GmbH	www.unitrode.com
Unz	Unizon	
Upi	UPI Semiconductor	
USA	USA located producer	
Usr	V/O Elektronzagranpostavka	
UTC	Unisonic Technologies Co., LTD.	www.unisonic.com.tw
Vac	EG&G Vactec	
Val	Valvo (Philips Semiconductor)	eu2.semiconductors.com
Vis	Vishay Intertechnology, Inc.	www.vishay.com
Vtc	VTC Inc.	www.vtc.com
Wab	Walbern Devices, Inc.	
Wea	West Ace	
Wes	Western Electric Co.	
Wfb	Werk für Fernsehelektronik Berlin	
Whs	Westinghouse Electric Corporation	
Zel	Zetex Inc.	
Zex	Zetex Inc.	www.zetex.com
Zex	Zetex GmbH	www.zetex.com
Zil	Zilog, Inc.	www.zilog.com
Ztx	Zetex GmbH	www.zetex.com

	Transistor				Darlington				FET				
	1	2	3	4	1	2	3	4	1	2	3	4	
a	E	B	C		E2	B1	C1/2		S	G	D		a
b	E	C	B		E2	C1/2	B1		S	D	G		b
c	B	C	E		B1	C1/2	E2		G	D	S		c
d	B	E	C		-	-	-		G	S	D		d
e	C	B	E		C1/2	B1	E2		D	G	S		e
f	C	E	B		-	-	-		D	S	G		f
g	E	B	C	Geh	E2	B1	C1/2	Geh	S	G	D	Sub	g
h	E	C	B	Geh	E2	C1/2	B1	Geh	S	D	G	Sub	h
j	B	C	E	Geh	B1	C1/2	E2	Geh	G	D	S	Sub	j
k	B	E	C	Geh	-	-	-	-	-	-	-	-	k
l	C	B	E	Geh	-	-	-	-	D	G	S	Sub	l
m	C	B	E	C	-	-	-	-	D	S	G	Sub	m
n	E	B	Geh	C	C1	E1/B2	E2		D	G	Sub	S	n
o	E	C	Geh	B	-	-	-	-	D	S	Sub	G	o
p	C	Geh	E	B	-	-	-	-	G	Sub	S	D	p
q	C	Geh	E	B	-	-	-	-	S	D	G	G	q
r	E	C	E	B	E2	B1	C1/2	E1/B2	S	G1	D	G2	r
s	E	B	E	C	E2	B1	E1/B2	C1/2	S	G1	G2	D	s
t	E	C	B	C	E2	E1/B2	B1	C1/2	D	G2	G1	S/Sub	t
u	E	B	C	B	B2	E1/2	C2/B1	C1	G1	G2	D	S/Sub	u
v	B	C	B	E	C1/2	E1/B2	B1	E2	S	D	G2	G1	v
w	B	E	B	C	B2	E1/2	C1	C2/B1	G1	G2	S	D	w
x	E	B	C	E	E2	B1	C1/2	E2	D	S	G1	G2	x
y	E	B	E2	C	-	-	-	-	S	G	S	D	y
z	E1	B	C	E2					S	D	S	G	z
za	B	E	C	E					G	S	D	S	za
zb	E1	C	A	B					G		D	S	zb
zc	E2	E1	C1	B1/2 C2					G2	D	S	G1	zc
zd	input	U_B	output	Gnd					G2	D	G1	S	zd
ze	C	E	B	E					S	S	G	D	ze
zf	C	B	E	B					G	-	S	D	zf
zg	C	-	B	E					G	D	S	D	zg
zh	B		E	C					G	S	S	D	zh
zj	E1/2	C2	B1/2	C1									zj
zk	E	E	B	C									zk
zm	output	U_B	U_B	input									zm
zn	E		B	C									zn



NPN



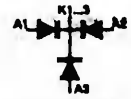
PNP

Weitere Pincode links Seite
Continuation on the left side

Weitere Pincode links Seite
Continuation on the left side

Diode

	1	2	3	4
a	A	K		
aa	K1	-	K2	A1-2
ab	A1		A2	K1-2
ac	A1		K2	K1/A2
al	A	K	A	K
b	K	A		
c	A	-	K	
c1	A	A	K	
c2	A1/K2		A2/K1	
c3	K2		A1	
d	K	-	A	
d1	K	K	A	
e	A	K	K	
f	K	A	A	
g	A	K	Geh	
h	K	A	Geh	
i	A	K	A	
j	A	K	A	K
j4	-	A	K	A
j5	A1	A2	A1	A2
j6	A1/K2	K1	A2	
j7	K1/K2	A1	A2	
j8	A1/K2	K1	A2	
l	A1	A2	K1-2	
ll	K1-2	A2	A1	
lk	A1		A2	K1-2
m	K1	K2	A1-2	
m1	A1-2	K2	K1	
m2	K1	A1/K2	K2	
n	A1	K2	A2/K1	
n1	A1	A2/K1	K2	
n2	A2/K1	K2	A1	
o	K1	A1/K2	A2	
o1	A1	K2	A2/K1	
o2	K2	A1	A2/K1	
o4	K1	A1/K2	A2	A1/K2
p	K1	K2	A1	
q	K2	A1-2	K1	
r	A1	A2	A3	K1-3
r1	A1	K2	K3	A3
r2	K1-3	A1	A2	K3
r3	A1-3	K1	K2	K3
s	K1	K2	K3	A1-3
s1	A1	K1	K2	K3
s2	A1	A2	K2	K1
s3	K1	A1	A2	K2
s4	K1	K2	A1	A2
s5	K1	A2	K2	A1
s6	K1	A2	K2	A1
s7	A1	A2	K1	K2
s8	A1	K2	A1	A2
s9	A1	K2	K1	A2
t	K	-	A	Geh
t1	A	-	K	Geh
t2	K	K	A	K
t3	A	A	A	K
t4	A	-	A	K
t5	K	-	A	K
t6	A2/K1	K2	Geh	A1
v	A	A	K	K
v1	K	K	A	A
x				
x1	+	-	-	-
x2	+	-	-	-
x3				
x4				
x5	-	+	-	-
x6	-	+	-	-
x7				
x8	A1/K2	A2/K1	Geh	A1
z	Aufdruckimprint Impr.			
	⇨Weitere Pincode linke Seite			



Pin-Code: ba



Pin-Code:
x, x1, x2, x3, x4, bn



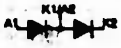
Pin-Code:
r, r1, r2, cc, ce, cg,
cj, de, dc



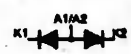
Pin-Code: y



Pin-Code:
s, s1, cd, cf, ch, ck, db



Pin-Code:
n, n1, o, o1, u, u1, bm, cm, bo



Pin-Code:
m, m1, q

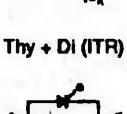


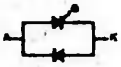
Pin-Code:
p, l, l1











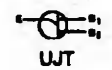














Thyristor,Triac*, PUT

	1	2	3	4
a	K	G	A	
b	K	A	G	
c	G	A	K	
d	G	K	A	
e	A	G	K	
f	A	K	G	
g	K	G	A	Geh
gl	K	A	G	Geh
h1	K	A	G	A
j	G	A	K	Geh
k	G	K	A	Geh
kl	A	G	K	Geh
m	A	K	G	Geh
n	K	-	G	A
o	A	K	A	G
p	A	A	G	K
q	T1	T2	G	T2
r	A1	G	A2	
s	A1	A2	G	
§	A + Geh./case/bolter/invol.			
&	K + Geh./case/bolter/invol.			
*	K= A1 (Triac)			
	A= A2 (Triac)			

Tetroden

a	K	Gk	Ga	A
b	A	K	Ga	Ga
c	Gk	K	Ga	A
d	K	Gk	A	Ga
e	Gk	K	A	Ga
f	K	Ga	Gk	A
§	Ga + Geh./case/bolter/invol.			

Trigger-Di, Diac**, UJT

a	A	K		
b	K	A		
c	A	-	K	
d	K	-	A	
e	A2	G	A1	
f	A2	A1	G	
g	K	G	A	
h	A	K	G	
m	B1	-	B2	E
n	B1	E	B2	
o	B2	E	B1	
p	E	B1	B2	
q	B1	B2	E	
r	E	B1	B2	
s	E	B2	B1	
t	B2	B1	E	
§	A2 + Geh./case/bolter/invol.			
&	G + Geh./case/bolter/invol.			
**	K= A1 (Diac)			
	A= A2 (Diac)			

Z-IC

a	output	input	Gnd	
b	Reg	Gnd	output	(Gnd)
c	Gnd	input	output	(input)
d	output	Gnd	input	
e	input	output	Gnd	
f	Gnd	output	input	
g	A	-	K	
h	A	K		
i	K	-	A	
k	input	Reg	output	
l	reg	output	input	
m	output	Reg	input	
n	reg	input	output	
o	input	output	Reg	

* Reg = Regelungsteil

Параметры электронных полупроводниковых приборов и интегральных микросхем

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
01...0Z					
0	C-Di	=HVC300A(Typ-Code/Stempel/marking)	71(1,3mm)	Hit	→HVC300A
0	C-Di	=HVE300A(Typ-Code/Stempel/marking)	71(1,3mm)	Hit	→HVE300A
0	C-Di	=HVU300(A)(Typ-Code/Stempel/marking)	71(1,7mm)	Hit	→HVU300(A)
00	Z-Di	=MM3Z2V4(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
01	MOS-P-FET-e	=GF2301(Typ-Code/Stempel/marking)	35	Gsi	→GF2301
01	Z-Di	=MM3Z2V7(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
01	Si-P+R	=PDTA143EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA143EE
01	Si-P+R	=PDTA143EK(Typ-Code/Stempel/marking)	35	Phi	→PDTA143EK
01-	Si-P+R	=PDTA143EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA143EU
010	Si-N	=S0918R(Typ-Code/Stempel/marking)	35	Tho	→S0918R
0104BA..0104NA..	Triac	=Z0101BA..0101NA:Igt/Ih<5/10mA	7a	Tag	-
015AZ2.0..12(X,Y,Z) .	Z-Di	2,0..12V,±2,5%,0,2W	71a(1,2mm)	Tos	-
015AZ2.0..12X,Y,Z	Z-Di	SMD,2,0..12V,?n2,5%,0,2W	71a(1,2mm)	Tos	-
015Z2.0..12(X,Y,Z)	Z-Di	2,0..12V,±2,5%,0,2W	71a(1,2mm)	Tos	-
015Z2.0..12X,Y,Z ..	Z-Di	SMD,2,0...12V,?n2,5%,0,2W	71a(1,2mm)	Tos	-
01A	Si-P+R	=RA101C(Typ-Code/Stempel/marking)	35	Say	→RA101C
01C	Si-N+R	=RC101C(Typ-Code/Stempel/marking)	35	Say	→RC101C
01N50M2	MOS-N-FET-e	=SPD01N50M2(Typ-Code/Stempel/marking)	30	Sie	→SPD01N50M2
01N50M2	MOS-N-FET-e	=SPN01N50M2(Typ-Code/Stempel/marking)	48	Sie	→SPN01N50M2
01N50M2	MOS-N-FET-e	=SPU01N50M2(Typ-Code/Stempel/marking)	30	Sie	→SPU01N50M2
01N60S5	MOS-N-FET-e	=SPD01N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPD01N60S5
01N60S5	MOS-N-FET-e	=SPN01N60S5(Typ-Code/Stempel/marking)	48	Sie	→SPN01N60S5
01N60S5	MOS-N-FET-e	=SPU01N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPU01N60S5
01t	Si-P+R	=PDTA143EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA143EU
02	MOS-N-FET-e	=BST82(Typ-Code/Stempel/marking)	35	Phi,Val	→BST82
02	Si-N	=BSX39(Typ-Code/Stempel/marking)	35	Mot	→BSX39
02	Z-Di	=MM3Z3V0(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
02	Si-N+R	=PDTC143EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC143EE
02	Si-N+R	=PDTC143EK(Typ-Code/Stempel/marking)	35	Phi	→PDTC143EK
02	Z-Di	=UDZ2.0B(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
-02	Si-N+R	=PDTC143EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC143EU
028	Si-N	=S03572R(Typ-Code/Stempel/marking)	35	Tho	→S03572R
02BZ2.2..4.7	Z-Di	2,2..4,7V,10%,0,25W	31a	Tos	BZX46/..,BZX55/..,BZX83/..,ZPD..,+
02CZ2.0..47(X,Y,Z)	Z-Di	2..47V,±5%,0,2W	35e	Tos	BZX84/..BZX88/..
02CZ2.0..47X,Y,Z ..	Z-Di	SMD,2..47V,?5%,0,2W	35e	Tos	BZX84/..,BZX88/..
02DZ2.0..47(X,Y,Z)	Z-Di	4,7..8,2V,±2,5%,0,2W	71a(1,7mm)	Tos	-
02DZ2.0..47X,Y,Z ..	Z-Di	SMD,2,0..24V,?n2,5%,0,2W	71a(1,7mm)	Tos	-
02N03L08	MOS-N-FET-e	=SPD30N03S2L-08(Typ-Code/Stempel)	30	Sie	→SPD30N03S2L-08
02N60S5	MOS-N-FET-e	=SPB02N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB02N60S5
02N60S5	MOS-N-FET-e	=SPD02N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPD02N60S5
02N60S5	MOS-N-FET-e	=SPN02N60S5(Typ-Code/Stempel/marking)	48	Sie	→SPN02N60S5
02N60S5	MOS-N-FET-e	=SPP02N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP02N60S5
02N60S5	MOS-N-FET-e	=SPU02N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPU02N60S5
02p	MOS-N-FET-e	=BST82(Typ-Code/Stempel/marking)	35	Phi	→BST82
03	Z-Di	=MSCT03(Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
03	Si-P+R	=PDTA114EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA114EE
03	Si-P+R	=PDTA114EEF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA114EEF
03	Si-P+R	=PDTA114EK(Typ-Code/Stempel/marking)	35	Phi	→PDTA114EK
-03	Si-P+R	=PDTA114EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA114EU
03C	Z-Di	=MSCT03C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
03C100PH	Z-Di	=BZG03-C100(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C10PH	Z-Di	=BZG03-C10(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C110PH	Z-Di	=BZG03-C110(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C11PH	Z-Di	=BZG03-C11(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C120PH	Z-Di	=BZG03-C120(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C12PH	Z-Di	=BZG03-C12(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
03C130PH	Z-Di	=BZG03-C130(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C13PH	Z-Di	=BZG03-C13(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C150PH	Z-Di	=BZG03-C150(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C15PH	Z-Di	=BZG03-C15(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C160PH	Z-Di	=BZG03-C160(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C16PH	Z-Di	=BZG03-C16(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C180PH	Z-Di	=BZG03-C180(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C18PH	Z-Di	=BZG03-C18(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C200PH	Z-Di	=BZG03-C200(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C20PH	Z-Di	=BZG03-C20(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C220PH	Z-Di	=BZG03-C220(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C22PH	Z-Di	=BZG03-C22(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C240PH	Z-Di	=BZG03-C240(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C24PH	Z-Di	=BZG03-C24(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C270PH	Z-Di	=BZG03-C270(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C27PH	Z-Di	=BZG03-C27(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C30PH	Z-Di	=BZG03-C30(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C33PH	Z-Di	=BZG03-C33(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C36PH	Z-Di	=BZG03-C36(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C39PH	Z-Di	=BZG03-C39(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C43PH	Z-Di	=BZG03-C43(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C47PH	Z-Di	=BZG03-C47(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C51PH	Z-Di	=BZG03-C51(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C56PH	Z-Di	=BZG03-C56(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C62PH	Z-Di	=BZG03-C62(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C68PH	Z-Di	=BZG03-C68(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C75PH	Z-Di	=BZG03-C75(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C82PH	Z-Di	=BZG03-C82(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03C91PH	Z-Di	=BZG03-C91(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG03-C..
03N06C	MOS-N-FET-e	=RLD03N06CLE(Typ-Code/Stempel/marking)	30	Rca	→RLD03N06CLE
03N06CLE	MOS-N-FET-e	=RLP03N06CLE(Typ-Code/Stempel/marking)	17	Rca	→RLP03N06CLE
03N60S5	MOS-N-FET-e	=SPB03N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB03N60S5
03N60S5	MOS-N-FET-e	=SPD03N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPD03N60S5
03N60S5	MOS-N-FET-e	=SPN03N60S5(Typ-Code/Stempel/marking)	48	Sie	→SPN03N60S5
03N60S5	MOS-N-FET-e	=SPP03N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP03N60S5
03N60S5	MOS-N-FET-e	=SPU03N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPU03N60S5
03P05M	50Hz-Thy	50V,0,5A,Igt/Ih <0,2/<5mA,25?s	7b	Nec	BT149/..,TAG59-..,2N6681..85
03P1M	50Hz-Thy	=03P05M:100V	7b	-	BT149/..,TAG59-..,2N6681..85
03P2J	50Hz-Thy	200V,0,3A(Ta=100oC),Igt/Ih <0,2/<5mA	39b	Nec	-
03P2M	50Hz-Thy	=03P05M:200V	7b	-	BT149/..,TAG59-..,2N6682..85
03P3M	50Hz-Thy	=03P05M:300V	7b	-	BT149/..,TAG59-..,2N6683..85
03P4J	50Hz-Thy	=03P2J:400V	39b	-	-
03P4M	50Hz-Thy	=03P05M:400V	7b	-	BT149/..,TAG59-..,2N6683..85
03P4MG(C)	50Hz-Thy	400V,0,3A(Tc=30oC),Igt/Ih <0,05/<5mA	7b	Nec	BT149/..,MCR606-..,TAG59-..
03P5J	50Hz-Thy	=03P2J:500V	39b	-	-
03P5M	50Hz-Thy	=03P05M:500V	7b	-	BT149/..,TAG59-..,2N6684..85
03P5MG(C)	50Hz-Thy	=03P4MG:500V	7b	-	BT149/..,MCR606-..,TAG59-..
04	Si-N+R	=PDTC114EK(Typ-Code/Stempel/marking)	35	Phi	→PDTC114EK
-04	Si-N	=PMSS3904(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSS3904
04100PH	Z-Di	=BZG04-100(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0410PH	Z-Di	=BZG04-10(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04110PH	Z-Di	=BZG04-110(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0411PH	Z-Di	=BZG04-11(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04120PH	Z-Di	=BZG04-120(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0412PH	Z-Di	=BZG04-12(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04130PH	Z-Di	=BZG04-130(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0413PH	Z-Di	=BZG04-13(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04150PH	Z-Di	=BZG04-150(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0415PH	Z-Di	=BZG04-15(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04160PH	Z-Di	=BZG04-160(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0416PH	Z-Di	=BZG04-16(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04180PH	Z-Di	=BZG04-180(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0418PH	Z-Di	=BZG04-18(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04200PH	Z-Di	=BZG04-200(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..

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0420PH	Z-Di	=BZG04-20(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04220PH	Z-Di	=BZG04-220(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0422PH	Z-Di	=BZG04-22(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0424PH	Z-Di	=BZG04-24(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0427PH	Z-Di	=BZG04-27(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0430PH	Z-Di	=BZG04-30(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0433PH	Z-Di	=BZG04-33(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0436PH	Z-Di	=BZG04-36(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0439PH	Z-Di	=BZG04-39(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
044	Si-N	=SO3571R(Typ-Code/Stempel/marking)	35	Tho	→SO3571R
0443PH	Z-Di	=BZG04-43(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0447PH	Z-Di	=BZG04-47(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0451PH	Z-Di	=BZG04-51(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0456PH	Z-Di	=BZG04-56(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0462PH	Z-Di	=BZG04-62(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0468PH	Z-Di	=BZG04-68(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
047	Si-N	=SO3570R(Typ-Code/Stempel/marking)	35	Tho	→SO3570R
0475PH	Z-Di	=BZG04-75(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0482PH	Z-Di	=BZG04-82(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
048V2PH	Z-Di	=BZG04-8V2(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
0491PH	Z-Di	=BZG04-91(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
049V1PH	Z-Di	=BZG04-9V1(Typ-Code/Stempel/marking)	71(5x2,5)	Phi	→BZG04-..
04A	Si-P+R	=RA104C(Typ-Code/Stempel/marking)	35	Say	→RA104C
04AZ2.0..39R..Z	Z-Di	2,0..39V,?n5%,3W	31a	Tos	BZV16/..,BZV47/..,BZX70/..,ZY..,+
04BZ5.1..24(XYZ)	Z-Di	ra,5,1..24V,n5%,0,4W	-	Tos	BZV39/..,1N4099..4116
04C	Si-N+R	=RC104C(Typ-Code/Stempel/marking)	35	Say	→RC104C
04DZ2.0..5.1(XYZ)	Z-Di	2,0..5,1V,n5%,0,4W	-	Tos	BZX46/..,BZX55/..,BZX83/..,ZPD..,+
04N60S5	MOS-N-FET-e	=SPB04N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB04N60S5
04N60S5	MOS-N-FET-e	=SPD04N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPD04N60S5
04N60S5	MOS-N-FET-e	=SPN04N60S5(Typ-Code/Stempel/marking)	48	Sie	→SPN04N60S5
04N60S5	MOS-N-FET-e	=SPP04N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP04N60S5
05	MOS-N-FET-e	=GF2304(Typ-Code/Stempel/marking)	35	Gsl	→GF2304
05	Z-Di	=MM3Z3V3(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
05	Z-Di	=MSCT05(Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
05	Si-P+R	=PDTA124EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA124EE
05	Si-P+R	=PDTA124EK(Typ-Code/Stempel/marking)	35	Phi	→PDTA124EK
05	Z-Di	=UDZ10B(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
05	Z-Di	=UDZS10B(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZS5.1B..10B
-05	Si-P+R	=PDTA124EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA124EU
05AZ2.2..100R..Z	Z-Di	2,2..100V,?n5%,0,5W	31a	Tos	BZX46/..,BZX55/..,BZX83/..,ZPD..,+
05C	Z-Di	=MSCT05C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
05F	Si-N	=TSDF1205R(Typ-Code/Stempel/marking)	44	Aeg	→TSDF1205
05J25	SI-Di	=SS05J25(Typ-Code/Stempel/marking)	31	Org	→SS05J25
06	Z-Di	=MM3Z3V6(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
06	Si-N+R	=PDTC124EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC124EE
06	Si-N+R	=PDTC124EK(Typ-Code/Stempel/marking)	35	Phi	→PDTC124EK
-06	Si-N+R	=PDTC124EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC124EU
-06	Si-P	=PMSS3906(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSS3906
066	Si-N	=SO269R(Typ-Code/Stempel/marking)	35	Tho	→SO269R
07	Z-Di	=KL3L07(Typ-Code/Stempel/marking)	71(5x2,5)	Shi	→KL3L07
07	Z-Di	=KL3LU07(Typ-Code/Stempel/marking)	71(5x2,5)	Shi	→KL3LU07
07	Z-Di	=MM3Z3V9(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
07	Si-P+R	=PDTA144EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA144EE
07	Si-P+R	=PDTA144EEF(Typ-Code/Stempel/marking	35(1,6mm)	Phi	→PDTA144EEF
07	Si-P+R	=PDTA144EK(Typ-Code/Stempel/marking)	35	Phi	→PDTA144EK
-07	Si-P+R	=PDTA144EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA144EU
07N60S5	MOS-N-FET-e	=SPB07N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB07N60S5
07N60S5	MOS-N-FET-e	=SPD07N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPD07N60S5
07N60S5	MOS-N-FET-e	=SPI07N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPI07N60S5
07N60S5	MOS-N-FET-e	=SPP07N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP07N60S5
07N60S5	MOS-N-FET-e	=SPU07N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPU07N60S5
08	Z-Di	=MM3Z4V3(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
08	Z-Di	=MSCT08(Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
08	Si-N+R	=PDTC144EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC144EE

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08	Si-N+R	=PDTC144EEF(Typ-Code/Stempel/marking	35(1,6mm)	Phi	→PDTC144EEF
08	Si-N+R	=PDTC144EK(Typ-Code/Stempel/marking)	35	Phi	→PDTC144EK
-08	Si-N+R	=PDTC144EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC144EU
087	Si-N	=S0502SR(Typ-Code/Stempel/marking)	35	Tho	→S0502SR
08C	Z-Di	=MSCT08C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
09	Si-Di	=1SS377(Typ-Code/Stempel/marking)	35	Tos	→1SS377
09	Si-Di	=1SS378(Typ-Code/Stempel/marking)	35(2mm)	Tos	→1SS378
09	Si-Di	=1SS385(Typ-Code/Stempel/marking)	35(1,6mm)	Tos	→1SS385
09	Si-Di	=1SS385F(Typ-Code/Stempel/marking)	35(1,6mm)	Tos	→1SS385F
09	Z-Di	=MM3Z4V7(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
09	Si-N+R	=PDTC114EE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC114EE
09	Si-N+R	=PDTC114EEF(Typ-Code/Stempel/marking	35(1,6mm)	Phi	→PDTC114EEF
-09	Si-N+R	=PDTC114EU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC114EU
091	Si-N	=S0642R(Typ-Code/Stempel/marking)	35	Tho	→S0642R
0A	Z-Di	=MM3Z5V1(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0A	Si-P+R	=MUN5111DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5111DW1
0B	Si-P+R	=MUN5112DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5112DW1
0C	Z-Di	=MM3Z5V6(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0C	Si-P+R	=MUN5113DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5113DW1
0D	Si-P+R	=MUN5114DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5114DW1
0E	Z-Di	=MM3Z6V2(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0E	Si-P+R	=MUN5115DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5115DW1
0F	Z-Di	=MM3Z6V8(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0F	Si-P+R	=MUN5116DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5116DW1
0G	Z-Di	=MM3Z7V5(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0G	Si-P+R	=MUN5130DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5130DW1
0H	Z-Di	=MM3Z8V2(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0H	Si-P+R	=MUN5131DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5131DW1
0J	Si-P+R	=MUN5132DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5132DW1
0K	Z-Di	=MM3Z9V1(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0K	Si-P+R	=MUN5133DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5133DW1
0L	Z-Di	=MM3Z10V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0L	Si-P+R	=MUN5134DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5134DW1
0M	Z-Di	=MM3Z11V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0M	Si-P+R	=MUN5135DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5135DW1
0N	Z-Di	=MM3Z12V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0N	Si-P+R	=MUN5136DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5136DW1
0P	Z-Di	=MM3Z13V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0P	Si-P+R	=MUN5137DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5137DW1
0T	Z-Di	=MM3Z15V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0U	Z-Di	=MM3Z16V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0W	Z-Di	=MM3Z18V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
0Z	Z-Di	=MM3Z20V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1...10...19					
1	C-Di	=BA277(Typ-Code/Stempel/marking)	71(1,3mm)	Phi	→BA277
1	C-Di	=BB669(Typ-Code/Stempel/marking)	71(1,7mm)	Sie	→BB669
1	Si-Di	=HSR101(Typ-Code/Stempel/marking)	71(2,7mm)	Hit	→HSR101
1	C-Di	=HVR187(Typ-Code/Stempel/marking)	71(2,7mm)	Hit	→HVR187
1,5KE6.8..440(A,P)	Z-Di	TAZ,6,8..440V,1,5kW(1ms)	31a	Gie,Mot,Tho	1N5629..65,1N6267..6303
1,5KE6.8..440(C,CA)	Z-Di/TVS	TAZ,6,8..440V,1,5kW(1µS),Bidirectional	31a	Gie,Mot,Tho	1N6036..72,1N6138..73
1,5KE6.8..440C,CA	Z-Di	bidirektional/backtoback	31a	-	1N6036..72,1N6138..73
1.5J4	Si-Di	=SS1.5J4(Typ-Code/Stempel/marking)	31	Org	→SS1.5J4
1.5J5	Si-Di	=SS1.5J5(Typ-Code/Stempel/marking)	31	Org	→SS1.5J5
1.5SMC6.8A..91A	Z-Di	SMD,TAZ,6,8..91V,5%,1500W(1ms)	71a(7,9mm)	Ons	-
1/4M...Z10	Z-Di	n10%	31a	-	BZX55/..,BZX83/..,ZPD..,1N5221..81,+
1/4M...Z5	Z-Di	n5%	31a	-	BZX55/..,BZX83/..,ZPD..,1N5221..81,+
1/4M10..175Z	Z-Di	10V..175V,0,5W,20%	31a	Motorola	1N5521..81,BZX55/..,BZX83/..NTE5019A
1/4M10..175Z1	Z-Di	10V..175V,0,5W,1%	31a	Motorola	1N5521..81,BZX55/..,BZX83/..NTE5019T1
1/4M10..175Z10	Z-Di	10V..175V,0,5W,10%	31a	Motorola	1N5521..81,BZX55/..,BZX83/..NTE5019A
1/4M10..175Z2	Z-Di	10V..175V,0,5W,2%	31a	Motorola	1N5521..81,BZX55/..,BZX83/..NTE5051A
1/4M10..175Z5	Z-Di	10V..175V,0,5W,5%	31a	Motorola	1N5521..81,BZX55/..,BZX83/..NTE5051A
1/4M2.4..200(A)Z	Z-Di	2,4..200V,0,25W,n20%	31a	Mot	BZX55/..,BZX83/..,ZPD..,1N5221..81,+
10	Si-Di	=1PS59SB10(Typ-Code/Stempel/marking)	35	Phi	→1PS59SB10

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10	Z-Di	=MAZF100(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MAZF100
10	Z-Di	=MAZN100(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZN100
10	Z-Di	=MAZS100(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS100
10	Z-Di	=MM3Z22V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
10	Si-N	=MRF9411(Typ-Code/Stempel/marking)	44	Mot	→MRF9411
10	N-FET	=SST110(Typ-Code/Stempel/marking)	35	Six	→SST110
10(X,Y,Z)	Z-Di	=U02W10V(Typ-Code/Stempel/marking)	35	Kec	→Z02W10V
10	Z-Di	=MA3A100(Typ-Code/Stempel/marking)	46	Mat	→MA3A100
10010	ECL Logic	Synchronous Decimal Up/Down Counter with Preset and Clear	10010	-	E10K, E95K
10014	ECL Logic	14-Bit Bus Termination Array	10014	-	E10K
10016	ECL Logic	Synchronous Binary 4-Bit Up Counter with Preset and Clear	10016	-	E10K, E10KH, E95K
10029	ECL Logic	Positive Edge Triggered JK Flip-Flop with Preset and Clear	10029	-	E95K
1006	Se-Di	→AEG1006	31a	Aeg	-
100A	Z-Di	=P6SMB100A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
100PH	Z-Di	=BZD23-C100(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
100PH	Z-Di	=BZD27-C100(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
100T2	Si-N	NF/S-L, 120V, 5A, 85W	23a$	Tho	BD245D, BD550, 2N5759..60, 2SC2706, +
101	Si-P	=FC101(Typ-Code/Stempel/marking)	46	Say	→FC101
101	Si-P+Di	=FP101(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP101
10100	ECL Logic	>Quad 2-Input NOR Gate and Strobe	10100	-	E10K, E10KH
10101	ECL Logic	4x2-Input OR/NOR Gate	10101	-	E10K, E10KH, E95K
10102	ECL Logic	Triple 2-Input NAND Gate, 2-Input NOR/OR Gate	10102	-	E10K, E10KH, E95K
10103	ECL Logic	Triple 2-Input NAND Gate, 2-Input NOR/OR Gate	10103	-	E10K, E10KH, E95K
10104	ECL Logic	Triple 2-Input NAND and Quad 2-Input AND/NAND Gate	10104	-	E10K, E10KH
10105	ECL Logic	2x2/1x3-Input OR/NOR Gate	10105	-	E10K, E10KH, E95K
10106	ECL Logic	2x3/1x4-Input OR/NOR Gate	10106	-	E10K, E10KH, E95K
10107	ECL Logic	Triple 2-Input EX-OR/NOR Gate	10107	-	E10K, E10KH, E95K
10109	ECL Logic	1x4/1x5-Input OR/NOR Gate	10109	-	E10K, E10KH, E95K
10110	ECL Logic	Dual 3-Input 3-Output OR Gate	10110	-	E10K, E95K
10111	ECL Logic	Dual 3-Input 3-Output NOR Gate	10111	-	E10K, E95K
10113	ECL Logic	Quad 2-Input EX-OR Gate with Enable	10113	-	E10K, E10KH
10114	ECL Logic	Triple Differential Line Receiver	10114	-	E10K
10115	ECL Logic	Quad Differential Line Receiver	10115	-	E10K, E10KH, E95K
10116	ECL Logic	Triple Differential Line Receiver	10116	-	E10K, E10KH, E95K
10117	ECL Logic	Dual OR/AND/NAND Combination-Gate	10117	-	E10K, E10KH
10118	ECL Logic	Dual OR/AND Combination-Gate	10118	-	E10K, E10KH
10119	ECL Logic	OR/AND Combination-Gate with 3x3 and 1x4 Inputs	10119	-	E10K, E10KH
10121	ECL Logic	OR/AND/NAND Combination-Gate	10121	-	E10K, E10KH
10123	ECL Logic	3 Bus Drivers, inverting	10123	-	E10K, E10KH
10124	ECL Logic	Quad Level-Changer TTL to ECL, non inverting/inverting with Strobe	10124	-	E10K, E10KH, E95K
10125	ECL Logic	Quad Level-Changer TTL to ECL	10125	-	E10K, E10KH
10129	ECL Logic	Quad Bus Receiver	10129	-	E10K
10130	ECL Logic	Dual D-type Flip-Flop with Complementary Outputs and Common Clock	10130	-	E10K, E10KH, E95K
10131	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10131	-	E10K, E10KH
10132	ECL Logic	Dual 2-to-1 Data Selector/Multiplexer with Latch	10132	-	E10K
10133	ECL Logic	4-Bit D-Latch, non inverting	10133	-	E10K
10134	ECL Logic	Dual 2-to-1 Data Selector/Multiplexer with Latch	10134	-	E10K
10135	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10135	-	E10K, E10KH
10136	ECL Logic	Synchronous Binary 4-Bit Up/Down Counter with Preset	10136	-	E10K, E10KH
10137	ECL Logic	Synchronous Decimal Up/Down Counter with Preset	10137	-	E10K
10138	ECL Logic	Biquinary Counter	10138	-	E10K
10141	ECL Logic	4-Bit Shift Register with parallel Input/Output, right/left shifting	10141	-	E10K, E10KH
10145	ECL Logic	16x4-Bit Register File	10145	-	E10K, E10KH
10147	ECL Logic	128x1-Bit RAM	10147	-	E10K
10148	ECL Logic	64x1-Bit RAM	10148	-	E10K
1015	Interface-IC	2 Sensitive High-speed Differential Line Receivers	1015	-	uni
10153	ECL Logic	4-Bit D-Latch, non inverting	10153	-	E10K
10154	ECL Logic	4-Bit Binary Down Counter with Preset	10154	-	E10K
10158	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer	10158	-	E10K, E10KH
10159	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer with Enable	10159	-	E10K, E10KH
10160	ECL Logic	12-Bit Parity Generator/Parity Checker	10160	-	E10K, E10KH
10161	ECL Logic	Binary-to-Octal Decoder	10161	-	E10K, E10KH
10162	ECL Logic	Binary-to-Octal Decoder	10162	-	E10K, E10KH
10164	ECL Logic	8-to-1 Data Selector/Multiplexer with Enable	10164	-	E10K, E10KH

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10165	ECL Logic	3-Bit Binary Priority Encoder	10165	-	E10K, E10KH
10166	ECL Logic	5-Bit Magnitude Comparator	10166	-	E10K, E10KH
10168	ECL Logic	4-Bit D-Latch, non Inverting	10168	-	E10K
10170	ECL Logic	9+2-Bit Parity Generator/Parity Checker	10170	-	E10K
10171	ECL Logic	Dual Binary to 1-4 Decoder	10171	-	E10K, E10KH
10172	ECL Logic	Dual Binary to 1-4 Decoder	10172	-	E10K, E10KH
10173	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer with Latch	10173	-	E10K, E10KH
10174	ECL Logic	Dual 4-to-1 Data Selector/Multiplexer	10174	-	E10K, E10KH
10175	ECL Logic	5-Bit D-Latch, non inverting	10175	-	E10K, E10KH
10176	ECL Logic	Hex Positive Edge Triggered D Flip-Flop	10176	-	E10K, E10KH
10178	ECL Logic	Asynchronous Binary 4-Bit Up Counter with Preset and Clear	10178	-	E10K
10179	ECL Logic	Look-Ahead Carry Block	10179	-	E10K, E10KH
10180	ECL Logic	21-Bit Adder/Subtracteur	10180	-	E10K, E10KH
10181	ECL Logic	4-Bit Arithmetic/Logic Unit, Function Generator	10181	-	E10K, E10KH
10186	ECL Logic	6-Bit D-type Flip-flop with Clear, non inverting	10186	-	E10K, E10KH
10188	ECL Logic	Hex Buffer with Common Enable, non inverting	10188	-	E10K, E10KH
10189	ECL Logic	Hex Buffer with Common Enable, inverting	10189	-	E10K, E10KH
10192	ECL Logic	Quad Bus Driver, inverting/inverting, with Separate Enable	10192	-	E10K
10195	ECL Logic	Hex Buffer/Inverter	10195	-	E10K
10197	ECL Logic	Hex 2-Input AND Gate	10197	-	E10K
10198	ECL Logic	Post-Triggerable Monoflop	10198	-	E10K
102	Si-N	=FC102 (Typ-Code/Stempel/marking)	46	Say	→FC102
102	Si-N	=FH102 (Typ-Code/Stempel/marking)	46(2mm)	Say	→FH102
102	Si-P+Di	=FP102 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP102
10209	ECL Logic	1x4/1x5-Input OR/NOR Gate	10209	-	E10K, E10KH
10210	ECL Logic	Dual 3-Input 3-Output OR Gate	10210	-	E10K, E10KH
10211	ECL Logic	Dual 3-Input 3-Output NOR Gate	10211	-	E10K, E10KH
10212	ECL Logic	Dual 3-Input 3-Output OR/NOR Gate	10212	-	E10K
10216	ECL Logic	Triple Differential Line Receiver	10216	-	E10K
10230	ECL Logic	Dual D-type Flip-Flop with Complementary Outputs and Common Clock	10230	-	E10K
10231	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10231	-	E10K, E95K
103	Si-P	=FC103 (Typ-Code/Stempel/marking)	45	Say	→FC103
103	Si-N	=FH103 (Typ-Code/Stempel/marking)	46(2mm)	Say	→FH103
103	Si-P+Di	=FP103 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP103
1030	Interface-IC	4 Single-Ended RS-232 Low-Power Line Drivers with Shut-down and Strobe	1030	-	RS232
1032	Interface-IC	4 Single-Ended RS-232/RS-423 Low-Power Line Drivers (+5V)	1032	-	RS232
1039	Interface-IC	3 Single-Ended Inverting RS-232 Line Drivers/Receivers	1039	-	RS232
104	Si-N	=FC104 (Typ-Code/Stempel/marking)	45	Say	→FC104
104	Si-N	=FH104 (Typ-Code/Stempel/marking)	46(2mm)	Say	→FH104
104	Si-P+Di	=FP104 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP104
1045	Interface-IC	6 Programmable Level Translators	1045	-	RS232,uni
104T2	Si-N	NF/S-L, 60V, 5A, 85W	23a$	Tho	BD245A, BDV91, 2N4914..15, 2SD895, +
105	Si-P	=FC105 (Typ-Code/Stempel/marking)	46	Say	→FC105
105	Si-N	=FH105 (Typ-Code/Stempel/marking)	46(2mm)	Say	→FH105
105	Si-P+Di	=FP105 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP105
10500	ECL Logic	>Quad 2-Input NOR Gate and Strobe	10500	-	E10K
10501	ECL Logic	4x2-Input OR/NOR Gate	10501	-	E10K
10502	ECL Logic	Triple 2-Input NAND Gate, 2-Input NOR/OR Gate	10502	-	E10K
10503	ECL Logic	Triple 2-Input NAND Gate, 2-Input NOR/OR Gate	10503	-	E10K
10504	ECL Logic	Triple 2-Input NAND and Quad 2-Input AND/NAND Gate	10504	-	E10K
10505	ECL Logic	2x2/1x3-Input OR/NOR Gate	10505	-	E10K
10506	ECL Logic	2x3/1x4-Input OR/NOR Gate	10506	-	E10K
10507	ECL Logic	Triple 2-Input EX-OR/NOR Gate	10507	-	E10K
10509	ECL Logic	1x4/1x5-Input OR/NOR Gate	10509	-	E10K
10510	ECL Logic	Dual 3-Input 3-Output OR Gate	10510	-	E10K
10511	ECL Logic	Dual 3-Input 3-Output NOR Gate	10511	-	E10K
10513	ECL Logic	Quad 2-Input EX-OR Gate with Enable	10513	-	E10K
10514	ECL Logic	Triple Differential Line Receiver	10514	-	E10K
10515	ECL Logic	Quad Differential Line Receiver	10515	-	E10K
10516	ECL Logic	Triple Differential Line Receiver	10516	-	E10K
10517	ECL Logic	Dual OR/AND/NAND Combination-Gate	10517	-	E10K
10518	ECL Logic	Dual OR/AND Combination-Gate	10518	-	E10K
10519	ECL Logic	OR/AND Combination-Gate with 3x3 and 1x4 Inputs	10519	-	E10K
10521	ECL Logic	OR/AND/NAND Combination-Gate	10521	-	E10K

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10523	ECL Logic	3 Bus Drivers, inverting	10523	-	E10K
10524	ECL Logic	Quad Level-Changer TTL to ECL, non inverting/inverting with Strobe	10524	-	E10K
10525	ECL Logic	Quad Level-Changer TTL to ECL	10525	-	E10K
1053	PIN-Di	→TDA 1053	25a	-	-
10530	ECL Logic	Dual D-type Flip-Flop with Complementary Outputs and Common Clock	10530	-	E10K
10531	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10531	-	E10K
10532	ECL Logic	Dual 2-to-1 Data Selector/Multiplexer with Latch	10532	-	E10K
10533	ECL Logic	4-Bit D-Latch, non inverting	10533	-	E10K
10534	ECL Logic	Dual 2-to-1 Data Selector/Multiplexer with Latch	10534	-	E10K
10535	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10535	-	E10K
10536	ECL Logic	Synchronous Binary 4-Bit Up/Down Counter with Preset	10536	-	E10K
10537	ECL Logic	Synchronous Decimal Up/Down Counter with Preset	10537	-	E10K
10538	ECL Logic	Biquinary Counter	10538	-	E10K
10541	ECL Logic	4-Bit Shift Register with parallel Input/Output, right/left shifting	10541	-	E10K
10553	ECL Logic	4-Bit D-Latch, non inverting	10553	-	E10K
10554	ECL Logic	4-Bit Binary Down Counter with Preset	10554	-	E10K
10558	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer	10558	-	E10K
10559	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer with Enable	10559	-	E10K
10560	ECL Logic	12-Bit Parity Generator/Parity Checker	10560	-	E10K
10561	ECL Logic	Binary-to-Octal Decoder	10561	-	E10K
10562	ECL Logic	Binary-to-Octal Decoder	10562	-	E10K
10564	ECL Logic	8-to-1 Data Selector/Multiplexer with Enable	10564	-	E10K
10565	ECL Logic	3-Bit Binary Priority Encoder	10565	-	E10K
10566	ECL Logic	5-Bit Magnitude Comparator	10566	-	E10K
10568	ECL Logic	4-Bit D-Latch, non inverting	10568	-	E10K
10570	ECL Logic	9+2-Bit Parity Generator/Parity Checker	10570	-	E10K
10571	ECL Logic	Dual Binary to 1-4 Decoder	10571	-	E10K
10572	ECL Logic	Dual Binary to 1-4 Decoder	10572	-	E10K
10573	ECL Logic	Quad 2-to-1 Data Selector/Multiplexer with Latch	10573	-	E10K
10574	ECL Logic	Dual 4-to-1 Data Selector/Multiplexer	10574	-	E10K
10575	ECL Logic	5-Bit D-Latch, non inverting	10575	-	E10K
10576	ECL Logic	Hex Positive Edge Triggered D Flip-Flop	10576	-	E10K
10579	ECL Logic	Look-Ahead Carry Block	10579	-	E10K
10580	ECL Logic	21-Bit Adder/Subtracteur	10580	-	E10K
10581	ECL Logic	4-Bit Arithmetic/Logic Unit, Function Generator	10581	-	E10K
10586	ECL Logic	6-Bit D-type Flip-flop with Clear, non inverting	10586	-	E10K
10592	ECL Logic	Quad Bus Driver, inverting/inverting, with Separate Enable	10592	-	E10K
10595	ECL Logic	Hex Buffer/Inverter	10595	-	E10K
10597	ECL Logic	Hex 2-Input AND Gate	10597	-	E10K
106	Si-N	=FC 106 (Typ-Code/Stempel/marking)	46	Say	→FC106
106	Si-P+Di	=FP 106 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP106
10610	ECL Logic	Dual 3-Input 3-Output OR Gate	10610	-	E10K
10611	ECL Logic	Dual 3-Input 3-Output NOR Gate	10611	-	E10K
10612	ECL Logic	Dual 3-Input 3-Output OR/NOR Gate	10612	-	E10K
10616	ECL Logic	Triple Differential Line Receiver	10616	-	E10K
10631	ECL Logic	Dual Positive Edge Triggered JK Flip-Flop with Common Clock	10631	-	E10K
107	Si-P	=FC 107 (Typ-Code/Stempel/marking)	45	Say	→FC107
107	Si-P+Di	=FP 107 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP107
108	Si-N	=FC 108 (Typ-Code/Stempel/marking)	45	Say	→FC108
108	Si-P+Di	=FP 108 (Typ-Code/Stempel/marking)	45(5mm)	Say	→FP108
1080	Interface-IC	2 Single-Ended Inverting RS-232 Line Drivers/Receivers with Shut-down (+5V)	1080	-	RS232
1081	Interface-IC	2 Single-Ended Inverting RS-232 Line Drivers/Receivers (+5V)	1081	-	RS232
108T2	Si-N	=BDY57	23a$	Tho	→BDY57
109	Si-P	=FC 109 (Typ-Code/Stempel/marking)	46	Say	→FC109
109T2	Si-N	=BDY58	23a$	Tho	→BDY58
10A	Z-Di	=1.5SMC10A (Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
10A	Z-Di	=MMBZ10VA (Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
10A	Z-Di	=P6SMB10A (Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
10A	Z-Di	=PZM10NB2A (Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
10A	Ref-Z-IC	=ZXRE1004FF (Typ-Code/Stempel/marking	35	Ztx	→ZXRE1004
10B	Z-Di	=HZF10BP (Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF10BP
10B	Ref-Z-IC	=ZXRE1004EF (Typ-Code/Stempel/marking	35	Ztx	→ZXRE1004
10B4B41	Si-Br	100V, 10A	79x3	Tos	KBPC10-01

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10BG2C11	Si-Di	Dual,S-L,100V,10A(Tc=109o),<700ns	22I$	Tos	BYP20-100,BYT28-300
10BG2Z11	Si-Di	=10BG2C11:	22m&	Tos	-
10BL2C41	Si-Di	Dual,S-L,100V,10A,<45ns	17p$	Tos	BYP20-100,BYQ28-100
10C	Z-Di	=HZF10CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF10CP
10C	Ref-Z-IC	=ZXRE1004DF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE1004
10CL2C41(A)	Si-Di	Dual,S-L,200V,10A,<45ns,A:<35ns	17p$	Tos	BYP20-200,BYQ28-200
10CL2CZ41A	Si-Di	=10CL2C41A:Iso	17p	-	BYQ28F-200,BYQ28X-200
10D	Ref-Z-IC	=ZXRE1004CF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE1004
10D1..D10	Si-Di	D1=100,D2=200,D4=400,D6=600V,	-		-
10D1..D10	Si-Di	D8=800,D10=1000V	-		-
10D1..D10	Si-Di	GI,100..1000V,1A	31a	Inr	BY126..127,BY133..135,1N4001..4007+
10D4B41	Si-Br	200V,10A	79x3	Tos	KBPC10-02
10DC1..DC10	Si-Di	Dual,100..1000V,1,8A	-		→2x1N4001..4007
10DF1..DF8	Si-Di	DF1=100,DF2=200,DF4=400,DF6=600V,	-		-
10DF1..DF8	Si-Di	DF8=800V	-		-
10DF1..DF8	Si-Di	GI,S,100..800V,1A,100..200ns	31a	Inr	BYD33D..M,BYT52B..M,RGP10B..M,+
10DG2D11	Si-Di	Dual,S-L,200V,10A(Tc=109o),<700ns	22I$	Tos	BYP20-200,BYT28-300
10DG2Z11	Si-Di	=10DG2C11:	22m&	Tos	-
10DL2C41(A)	Si-Di	Dual,S-L,150V,10A,<45ns,A:<35ns	17p$	Tos	BYP20-150,BYQ28-150
10DL2C48A	Si-Di	=U10DL2C48A:	30p	Tos	→U10DL2C48A
10DL2CZ41A	Si-Di	=10CL2C41A:Iso	17p	-	BYQ28F-150,BYQ28X-510
10DL2CZ47A	Si-Di	Dual,L,S,200V,10A,<35ns	17p	Tos	BYQ28F-200,BYV32F-200
10E1..E8	Si-Di	E1=100,E2=200,E4=400,E6=600,E8=800V	-		-
10E1..E8	Si-Di	GI,100..800V,1A	31a	Inr	BY126..127,BY133..135,1N4001..4007+
10EF1..EF2	Si-Di	EF1=100V,EF2=200V	-		-
10EF1..EF2	Si-Di	GI,S,100..200V,1A,<200ns	31a	Inr	BYD33D..G,BYT52B..M,FE1B..H,+
10ELS1..ELS6	Si-Di	ELS1=100,ELS2=200,ELS4=400,ELS6=600V	-		-
10ELS1..ELS6	Si-Di	GI,S,100..600V,1A,<150ns	31a	Inr	BYT11-..,BYT52B..M,BYV26B..E,+
10F	Ref-Z-IC	=ZXRE4041FF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE4041
10FL2C48A	Si-Di	=U10FL2C48A:	30p	Tos	→U10FL2C48A
10FL2CZ41A	Si-Di	Dual,L,S,300V,10A,<35ns	17p	Tos	-
10FL2CZ47A	Si-Di	Dual,L,S,300V,10A,<35ns	17p	Tos	MA654,MA694
10FWJ2C11	Si-Di	Dual,Schottky,L,S,30V,10A(Tc=131o)	22I$	Tos	BYV18-30,BYV118-35
10FWJ2C11	Si-Di	Uf<0,68V(5A),<200ns	-		-
10FWJ2C41	Si-Di	Dual,Schottky,L,S,30V,10A(Tc=131o)	17p$	Tos	BYV18-30,BYV118-35
10FWJ2C41	Si-Di	Uf<0,68V(5A),<200ns	-		-
10FWJ2C42	Si-Di	Dual,Schottky,L,S,30V,10A(Tc=107o)	17p$	Tos	-
10FWJ2C42	Si-Di	Uf<0,55V(5A),<35ns	-		-
10FWJ2C48M	Si-Di	=U10FWJ2C48M:	30p	Tos	→U10FWJ2C48M
10FWJ2CZ42	Si-Di	=10FWJC42:Iso	17p	-	-
10FWJ2CZ47M	Si-Di	Dual,Schottky,L,S,30V,10A	17p	Tos	MA750(A)
10G	Ref-Z-IC	=ZXRE4041EF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE4041
10G4B41	Si-Br	400V,10A	79x3	Tos	KBPC10-04
10GG2C11	Si-Di	Dual,S-L,400V,10A(Tc=109o),<700ns	22I$	Tos	BYT28-400
10GG2Z11	Si-Di	=10GG2C11:	22m&	Tos	-
10GL2CZ47A	Si-Di	Dual,L,S,400V,10A,<35ns	17p	Tos	MA694
10GWJ2C11	Si-Di	Dual,Schottky,L,S,40V,10A(Tc=131o)	22I$	Tos	BYV18-40,BYV118-40
10GWJ2C11	Si-Di	Uf<0,68V(5A),<200ns	-		-
10GWJ2C41	Si-Di	Dual,Schottky,L,S,40V,10A(Tc=131o)	17p$	Tos	BYV18-40,BYV118-40
10GWJ2C41	Si-Di	Uf<0,68V(5A),<200ns	-		-
10GWJ2C42	Si-Di	Dual,Schottky,L,S,40V,10A(Tc=107o)	17p$	Tos	(BYS24-45,MBR2045CT)
10GWJ2C42	Si-Di	Uf<0,55V(5A),<35ns	-		-
10GWJ2C48C	Si-Di	=U10GWJ2C48C:	30p$	Tos	→U10GWJ2C48C
10GWJ2CZ42	Si-Di	=10GWJ2C42:Iso	17p	Tos	(BYS24-45,MBR2045CT)
10GWJ2CZ47M	Si-Di	Dual,Schottky,L,S,40V,10A	17p	Tos	MA750(A)
10H	Ref-Z-IC	=ZXRE4041DF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE4041
10J	Ref-Z-IC	=ZXRE4041CF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE4041
10J4B41	Si-Br	600V,10A	79x3	Tos	KBPC10-06
10JG2C11	Si-Di	Dual,S-L,600V,10A(Tc=109o),<700ns	22I$	Tos	BYR28-600
10JG2Z11	Si-Di	=10JG2C11:	22m&	Tos	-
10JL2CZ47A	Si-Di	Dual,L,S,600V,10A,<50ns	17p	Tos	-
10K	Z-Di	=MA3100WK(Typ-Code/Stempel/marking)	35	Mat	→MA3100WK
10KF10..KF40	Si-Di	GI/L-S,100..400V,10A,<35..45ns	17t$	Inr	BYT79-..
10KF10..KF40	Si-Di	KF10=100,KF20=200,KF30=300,KF40=400V	-		-

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10KF10B..KF40B...	Si-Di	=10KF10..KF40:	17t1	Inr	-
10L6	Z-Di	=KP10L06(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10L07
10L60	Si-Di	=DF10L60(Typ-Code/Stempel/marking)	30	Shi	→DF10L60
10L7	Z-Di	=KP10L07(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10L07
10L8	Z-Di	=KP10L08(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10L08
10LC20U	Si-Di	=DF10LC20U(Typ-Code/Stempel/marking)	30	Shi	→DF10LC20U
10LU06	Z-Di	=KP10LU06(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10LU06
10LU08	Z-Di	=KP10LU08(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10LU08
10N02Z	MOS-N-FET-e*...	=MMSF10N02Z(Typ-Code/Stempel/marking)	8-MDIP	Ons	→MMSF10N02Z
10N03Z	MOS-N-FET-e*...	=MMSF10N03Z(Typ-Code/Stempel/marking)	8-MDIP	Ons	→MMSF10N03Z
10N12	Z-Di	=KP10N12(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10N12
10N14	Z-Di	=KP10N14(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10N14
10N4	Z-Di	=KA10N14(Typ-Code/Stempel/marking)	31	Shi	→KA10N14
10P3	Si-Di	=DE10P3(Typ-Code/Stempel/marking)	30	Shi	→DE10P3
10PC3	Si-Di	=DE10PC3(Typ-Code/Stempel/marking)	30	Shi	→DE10PC3
10PH	Z-Di	=BZD23-C10(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
10PH	Z-Di	=BZD27-C10(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
10R25	Z-Di	=KP10R25(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP10R25
10R5	Z-Di	=KA10R25(Typ-Code/Stempel/marking)	31	Shi	→KA10R25
10S3	Si-Di	=DE10S3L(Typ-Code/Stempel/marking)	30	Shi	→DE10S3L
10SC3	Si-Di	=DE10SC3L(Typ-Code/Stempel/marking)	30	Shi	→DE10SC3L
10SC4	Si-Di	=DE10SC4(Typ-Code/Stempel/marking)	30	Shi	→DE10SC4
10SC4M	Si-Di	=DF10SC4M(Typ-Code/Stempel/marking)	30	Shi	→DF10SC4M
10SP-01..10	Si-Di	Dual,50..1000V,10A	?70	Gie	-
10W	Z-Di	=MA3100W(Typ-Code/Stempel/marking)	44	Mat	→MA3100W
10Y	Z-Di	=BZV49/C10(Typ-Code/Stempel/marking)	39	Val	→BZV49/C10
10Z6,8-M..47-M...	Z-Di	6,8..47V,6%,10W	-	Tos	-
11	N-FET	=FC11(Typ-Code/Stempel/marking)	45	Say	→FC11
11	Z-Di	=MAZF110(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MAZF110
11	Z-Di	=MAZN110(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZN110
11	Z-Di	=MAZS110(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS110
11	Z-Di	=MM3Z24V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
11	Si-Di	=MMBD1501(Typ-Code/Stempel/marking)	35	Nsc	→MMBD1501
11	Si-N	=MRF9511(Typ-Code/Stempel/marking)	44	Mot	→MRF9511
11	Si-N/P+R	=MUN5311DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5311DW1
11	Si-P+R	=PDTA114TU(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTA114TU
11	Si-P/N+R	=RN46A1(Typ-Code/Stempel/marking)	46	Tos	→RN46A1
11(X,Y,Z)	Z-Di	=U02W11V(Typ-Code/Stempel/marking)	35	Kec	→Z02W11V
110	Si-N	=FC110(Typ-Code/Stempel/marking)	46	Say	→FC110
110A	Z-Di	=P6SMB110A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
110PH	Z-Di	=BZD23-C110(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
110PH	Z-Di	=BZD27-C110(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
111	Si-P	=FC111(Typ-Code/Stempel/marking)	45	Say	→FC111
111T2	Si-N	S,60V,0,8W	2a$	Tho	-
111T2/18	Si-N	S,60V,0,5W	2a$	-	-
112	Si-N	=FC112(Typ-Code/Stempel/marking)	45	Say	→FC112
113	Si-P	=FC113(Typ-Code/Stempel/marking)	46	Say	→FC113
1130	Interface-IC	5 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(+5V)	1130	-	RS232
1131	Interface-IC	5 Single-Ended Drivers and 4 Single-Ended Receivers for RS-232 with Shut-down	1131	-	RS232
1132	Interface-IC	5 Single-Ended Drivers and 3 Single-Ended Receivers for RS-232(+5V)	1132	-	RS232
1133	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(+5V)	1133	-	RS232
1134	Interface-IC	4 Single-Ended Drivers and 4 Single-Ended Receivers for RS-232(+5V)	1134	-	RS232
1135	Interface-IC	5 Single-Ended Drivers and 3 Single-Ended Receivers for RS-232	1135	-	RS232
1136	Interface-IC	4 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(+5V)	1136	-	RS232
1137	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(+5V)	1137	-	RS232
1138	Interface-IC	5 Single-Ended Drivers and 3 Single-Ended Receivers for RS-232	1138	-	RS232
1139	Interface-IC	4 Single-Ended Drivers and 4 Single-Ended Receivers for RS-232(+5V/+12V)	1139	-	RS232
114	Si-N	=FC114(Typ-Code/Stempel/marking)	46	Say	→FC114
1140	Interface-IC	5 Single-Ended Drivers and 3 Single-Ended Receivers for RS-232	1140	-	RS232
1141	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	1141	-	RS232
1145	Interface-IC	Input/Output Insulator f?r TTL/CMOS Signals	1145	-	uni
1146	Interface-IC	Input/Output Insulator f?r TTL/CMOS Signals	1146	-	uni
115	Si-P	=FC115(Typ-Code/Stempel/marking)	45	Say	→FC115

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116	Si-N	=FC116(Typ-Code/Stempel/marking)	45	Say	→FC116
117	Si-P	=FC117(Typ-Code/Stempel/marking)	46	Say	→FC117
118	Si-N	=FC118(Typ-Code/Stempel/marking)	46	Say	→FC118
1180	Interface-IC	2Single-EndedInvertingLowPowerRS-232LineDrivers/Receivers(+5V)	1180	-	RS232
1181	Interface-IC	2Single-EndedInvertingLowPowerRS-232LineDrivers/Receivers(+5V)	1181	-	RS232
119	Si-N	=FC119(Typ-Code/Stempel/marking)	46	Say	→FC119
11A	Z-Di	=1.5SMC11A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
11A	Z-Di	=P6SMB11A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
11A	Z-Di	=PZM11NB2A(Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
11B	Z-Di	=HZF11BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF11BP
11C	Z-Di	=HZF11CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF11CP
11C	Z-Di	=P6SMB11CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
11D	Si-Di	=BYD11D(Typ-Code/Stempel/marking)	31	Phi	→BYD11..
11DF1..DF4	Si-Di	GI,S,100..400V,1A,30ns,DF1=100V,DF2=200V,DF3=300V,DF4=400V	31a	Inr	EGP10B..G,FE1B..H
11E1..E4	Si-Di	GI,100..400V,1A,E1=100V,E2=200V,E4=400V	31a	Inr	BY126..127,BY133..135,1N4001..4007+
11EFS1..EFS4	Si-Di	GI,S,100..400V,1A,<30ns,EFS1=100,EFS2=200,EFS3=300,EFS4=400V	31a	Inr	EGP10B..G,FE1B..H
11ES1..ES2	Si-Di	GI,100..200V,1A,ES1=100V,ES2=200V	31a	Inr	BY126..127,BY133..135,1N4001..4007+
11G	Si-Di	=BYD11G(Typ-Code/Stempel/marking)	31	Phi	→BYD11..
11J	Si-Di	=BYD11J(Typ-Code/Stempel/marking)	31	Phi	→BYD11..
11K	Si-Di	=BYD11K(Typ-Code/Stempel/marking)	31	Phi	→BYD11..
11M	Si-Di	=BYD11M(Typ-Code/Stempel/marking)	31	Phi	→BYD11..
11N60S5	MOS-N-FET-e	=SPB11N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB11N60S5
11N60S5	MOS-N-FET-e	=SPI11N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPI11N60S5
11N60S5	MOS-N-FET-e	=SPP11N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP11N60S5
11N60S5	MOS-N-FET-e	=SPW11N60S5(Typ-Code/Stempel/marking)	16	Sie	→SPW11N60S5
11PH	Z-Di	=BZD23-C11(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
11PH	Z-Di	=BZD27-C11(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
11Y	Z-Di	=BZV49/C11(Typ-Code/Stempel/marking)	39	Val	→BZV49/C11
12	Z-Di	=DF2S12FU(Typ-Code/Stempel/marking)	71(1,7mm)	Tos	→DF2S12FU
12	Si-N+N-FET	=FC12(Typ-Code/Stempel/marking)	45	Say	→FC12
12	Z-Di	=MAZF120(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MAZF120
12	Z-Di	=MAZN120(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZN120
12	Z-Di	=MAZS120(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS120
12	Z-Di	=MM3Z27V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
12	Z-Di	=MSCT12(Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
12	Si-N/P+R	=MUN5312DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5312DW1
12	Z-Di	=U1Z12(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z12
12	Z-Di	=UDZ2.2B(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
12(X,Y,Z)	Z-Di	=U02W12V(Typ-Code/Stempel/marking)	35	Kec	→Z02W12V
120	Si-N	=FC120(Typ-Code/Stempel/marking)	46	Say	→FC120
1200	SI-Di	-		-	-
120A	Z-Di	=P6SMB120A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
120PH	Z-Di	=BZD23-C120(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
120PH	Z-Di	=BZD27-C120(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
121	Si-P+R	=FC121(Typ-Code/Stempel/marking)	45	Say	→FC121
123	Si-P+R	=FC123(Typ-Code/Stempel/marking)	46	Say	→FC123
1237	Interface-IC	3Single-EndedDrivers and5Single-EndedReceiversforRS-232	1237	-	RS232
123PH	Si-Di	=BYD123(Typ-Code/Stempel/marking)	31	Phi	→BYD123
124	Si-N+R	=FC124(Typ-Code/Stempel/marking)	46	Say	→FC124
125	Si-P+R	=FC125(Typ-Code/Stempel/marking)	45	Say	→FC125
126	Si-N+R	=FC126(Typ-Code/Stempel/marking)	45	Say	→FC126
127	Si-P+R	=FC127(Typ-Code/Stempel/marking)	46	Say	→FC127
128	Si-P+R	=FC128(Typ-Code/Stempel/marking)	46	Say	→FC128
1280	Interface-IC	2Single-EndedInvertingLowPowerRS-232LineDrivers/Receivers(+5V)	1280	-	RS232
1281	Interface-IC	2Single-EndedInvertingLowPowerRS-232LineDrivers/Receivers(+5V)	1281	-	RS232
129	Si-P+R	=FC129(Typ-Code/Stempel/marking)	45	Say	→FC129
12A	Z-Di	=1.5SMC12A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
12A	Z-Di	=MA3120WA(Typ-Code/Stempel/marking)	35	Mat	→MA3120WA
12A	Z-Di	=MAZK120D(Typ-Code/Stempel/marking)	45	Mat	→MAZK1200
12A	Z-Di	=MMBZ12VA(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
12A	Z-Di	=MMQA12V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V

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12A	Z-Di	=P6SMB12A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
12A	Z-Di	=PZM12NB2A(Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
12B	Z-Di	=HZF12BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF12BP
12BL2C41	Si-Di	Dual,GI/S-L,100V,12A,<55ns	18p$	Tos	BYV72-100,BYW99P-100
12C	Z-Di	=HZF12CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF12CP
12C	Z-Di	=MSCT12C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
12C	Z-Di	=P6SMB12CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
12CL2C41	Si-Di	Dual,GI/S-L,150V,12A,<55ns	18p$	Tos	BYV72-150,BYW99P-150
12D	Z-Di	=MAZL120D(Typ-Code/Stempel/marking)	45	Mat	→MAZL1200
12DL2C41	Si-Di	Dual,GI/S-L,200V,12A,<55ns	18p$	Tos	BYV72-200,BYW99P-200
12DPH	Si-Di	=BYD12D(Typ-Code/Stempel/marking)	31	Phi	→BYD12..
12F	Ref-Z-IC	=ZXRE125FF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE125
12G	Si-N	=MSC2712G(Typ-Code/Stempel/marklng)	35	Ons	→MSC2712
12G	Ref-Z-IC	=ZXRE125EF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE125
12GPH	Si-Di	=BYD12G(Typ-Code/Stempel/marking)	31	Phi	→BYD12..
12H	Ref-Z-IC	=ZXRE125DF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE125
12J	Ref-Z-IC	=ZXRE125CF(Typ-Code/Stempel/marking	35	Ztx	→ZXRE125
12JPH	Si-Di	=BYD12J(Typ-Code/Stempel/marking)	31	Phi	→BYD12..
12KPH	Si-Di	=BYD12K(Typ-Code/Stempel/marking)	31	Phi	→BYD12..
12MPH	Si-Di	=BYD12M(Typ-Code/Stempel/marking)	31	Phi	→BYD12..
12PH	Z-Di	=BZD23-C12(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
12PH	Z-Di	=BZD27-C12(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
12Y	Z-Di	=BZV49/C12(Typ-Code/Stempel/marking)	39	Val	→BZV49/C12
13	Si-Di	=BAS125(Typ-Code/Stempel/marking)	35	Sie	→BAS125
13	N-FET	=FC13(Typ-Code/Stempel/marking)	46	Say	→FC13
13	Z-Di	=MAZS130(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS130
13	Si-Di	=MMBD1503(Typ-Code/Stempel/marking)	35	Nsc	→MMBD1503
13	Si-N/P+R	=MUN5313DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5313DW1
13	Z-Di	=U1Z13(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z13
13(X,Y,Z)	Z-Di	=U02W13V(Typ-Code/Stempel/marking)	35	Kec	→Z02W13V
130	Si-N+R	=FC130(Typ-Code/Stempel/marking)	45	Say	→FC130
1300	MOS-NP-FET-e...	=MMDF1300(Typ-Code/Stempel/marking)	8-MDIP	Ons	→MMDF1300
130A	Z-Di	=P6SMB130A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
130PH	Z-Di	=BZD23-C130(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
130PH	Z-Di	=BZD27-C130(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
131	Si-P+R	=FC131(Typ-Code/Stempel/marking)	46	Say	→FC131
132	Si-N+R	=FC132(Typ-Code/Stempel/marking)	46	Say	→FC132
1320	Interface-IC	RS-422/EIA-562 Apple Talk Transceiver	1320	-	RS562,RS422
1321	Interface-IC	2 RS-232/EIA-562 Transceivers and 2 RS-485 Transceivers	1321	-	RS232,RS422,RS562,RS485
1322	Interface-IC	4 RS-232/EIA-562 Transceivers and 2 RS-485 Transceivers	1322	-	RS232,RS422,RS562,RS485
1327	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for EIA-562(+3.3V)	1327	-	RS562
133	Si-P+R	=FC133(Typ-Code/Stempel/marking)	45	Say	→FC133
1330	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	1330	-	RS232
1331	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for 3V-EIA-562	1331	-	RS562,RS232
1332	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232 wit 12VVPP	1332	-	RS232
1335	Interface-IC	4 EIA-562 Transceivers and 2 RS-485 Transceivers with Output Enable	1335	-	RS422,RS562,RS485
1337	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	1337	-	RS232
1338	Interface-IC	5 Single-Ended Drivers and 3 Single-Ended Receivers for RS-232(Low Power)	1338	-	RS232
134	Si-N+R	=FC134(Typ-Code/Stempel/marking)	45	Say	→FC134
1341	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	1341	-	RS232
1342	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	1342	-	RS232
1347	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(Low Power)	1347	-	RS232
1349	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232(Low Power)	1349	-	RS232
135	Si-P+R	=FC135(Typ-Code/Stempel/marking)	46	Say	→FC135
1350	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for EIA-562(+3.3V)	1350	-	RS562
136	Si-N+R	=FC136(Typ-Code/Stempel/marking)	46	Say	→FC136
137	Si-P+R	=FC137(Typ-Code/Stempel/marking)	45	Say	→FC137
138	Si-N+R	=FC138(Typ-Code/Stempel/marking)	45	Say	→FC138
1381	Interface-IC	2 Single-Ended Inverting Low Power RS-232 Line Drivers/Receivers(+5V)	1381	-	RS232
1382	Interface-IC	2 Single-Ended Inverting Low Power RS-232 Line Drivers/Receivers	1382	-	RS232
1383	Interface-IC	2 Single-Ended Inverting Low Power RS-232 Line Drivers/Receivers(+5V)	1383	-	RS232
1384	Interface-IC	2 Single-Ended Inverting Low Power RS-232 Line Drivers/Receivers.	1384	-	RS232
1385	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for EIA-562(+3.3V)	1385	-	RS562

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1386	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for EIA-562 (+3.3V)	1386	-	RS562
139	Si-N	=FC139 (Typ-Code/Stempel/marking)	46	Say	→FC139
13A	Z-Di	=1.5SMC13A (Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
13A	Z-Di	=MA3130WA (Typ-Code/Stempel/marking)	35	Mat	→MA3130WA
13A	Z-Di	=MMQA13V (Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
13A	Z-Di	=P6SMB13A (Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
13A	Z-Di	=PZM13NB2A (Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
13B	Z-Di	=HZF13BP (Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF13BP
13C	Z-Di	=HZF13CP (Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF13CP
13C	Z-Di	=P6SMB13CA (Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
13DPH	Si-Di	=BYD13D (Typ-Code/Stempel/marking)	31	Phi	→BYD13..
13F	Si-N/P	=BC847BPDW1 (Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC847..PDW1
13G	Si-N/P	=BC847CPDW1 (Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC847..PDW1
13GPH	Si-Di	=BYD13G (Typ-Code/Stempel/marking)	31	Phi	→BYD13..
13JPH	Si-Di	=BYD13J (Typ-Code/Stempel/marking)	31	Phi	→BYD13..
13K	Si-N/P	=BC848BPDW1 (Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC848..PDW1
13KPH	Si-Di	=BYD13K (Typ-Code/Stempel/marking)	31	Phi	→BYD13..
13L	Si-N/P	=BC848CPDW1 (Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC848..PDW1
13MPH	Si-Di	=BYD13M (Typ-Code/Stempel/marking)	31	Phi	→BYD13..
13PH	Z-Di	=BZD23-C13 (Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
13PH	Z-Di	=BZD27-C13 (Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
13R	MOS-N-FET-d*	=S913TR (Typ-Code/Stempel/marking)	44	Aeg	→S913T
13s	Si-Di	=BAS125W (Typ-Code/Stempel/marking)	35(2mm)	Sie	→BAS125W
13t	Si-N/P	=BC847BPN (Typ-Code/Stempel/marking)	46	Phi	→BC847BPN
13Y	Z-Di	=BZV49/C13 (Typ-Code/Stempel/marking)	39	Val	→BZV49/C13
14	Si-Di	=1PS59SB14 (Typ-Code/Stempel/marking)	35	Phi	→1PS59SB14
14	Si-Di	=BAS125-04 (Typ-Code/Stempel/marking)	35	Sie	→BAS125-04
14	Z-Di	=KL3N14 (Typ-Code/Stempel/marking)	71(5x2,5)	Shi	→KL3N14
14	Z-Di	=MM3Z30V (Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
14	Si-Di	=MMBD1504 (Typ-Code/Stempel/marking)	35	Nsc	→MMBD1504
14	Si-N/P+R	=MUN5314DW1 (Typ-Code/Stempel/marking	46	Ons	→MUN5314DW1
140	Si-N	=FC140 (Typ-Code/Stempel/marking)	46	Say	→FC140
1401	Si-N	→ED1401	7a	-	-
1402	Si-N	→ED1402	7a	-	-
142	Si-P+R	=FC142 (Typ-Code/Stempel/marking)	45	Say	→FC142
142T	Si-N	?BD142	23a$	-	→BD142
143	Si-N+R	=FC143 (Typ-Code/Stempel/marking)	45	Say	→FC143
143PH	Si-Di	=BYD143 (Typ-Code/Stempel/marking)	31	Phi	→BYD143
144	Si-N+R	=FC144 (Typ-Code/Stempel/marking)	45	Say	→FC144
14535	Interface-IC	3 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232	14535	-	V.28,RS232
14561	Interface-IC	4 Single-Ended Drivers and 5 Single-Ended Receivers for EIA-562 (+3.3V)	14561	-	RS562,RS232
1480	Interface-IC	Insulated Differential RS-485/RS-422 Data Transceiver with Photocoupler	1480	-	RS485,RS422
149	Si-P	=FC149 (Typ-Code/Stempel/marking)	45	Say	→FC149
14A	Si-N	=MSD2714A (Typ-Code/Stempel/marking)	35	Ons	→MSD2714A
14B	Si-N	=BFR14B (Typ-Code/Stempel/marking)	52	Sie	→BFR14B
14C	Si-N	=BFR14C (Typ-Code/Stempel/marking)	51	Sie	→BFR14C
14N05L	MOS-N-FET-e	=RFD14N05L (Typ-Code/Stempel/marking)	30	Rca	→RFD14N05L
14N06L	MOS-N-FET-e	=RFD14N06L (Typ-Code/Stempel/marking)	30	Rca	→RFD14N06L
14s	Si-Di	=BAS125-04W (Typ-Code/Stempel/marking)	35(2mm)	Sie	→BAS125-04W
14s	Si-Di	=BAT114-099 (Typ-Code/Stempel/marking)	44	Sie	→BAT114-099
1S	Si-Di	=1PS59SB15 (Typ-Code/Stempel/marking)	35	Phi	→1PS59SB15
1S	Si-Di	=BAS125-05 (Typ-Code/Stempel/marking)	35	Sie	→BAS125-05
1S	Z-Di	=MAZS150 (Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS150
1S	Si-Di	=MMBD1505 (Typ-Code/Stempel/marking)	35	Nsc	→MMBD1505
1S	Si-N	=MMBT3960 (Typ-Code/Stempel/marking)	35	Mot	→MMBT3960
1S	Z-Di	=MSCT15 (Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
1S	Si-N/P+R	=MUN5315DW1 (Typ-Code/Stempel/marking	46	Ons	→MUN5315DW1
1S	Z-Di	=U1Z15 (Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z15
1S	Z-Di	=UDZ11B (Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
1S(X,Y,Z)	Z-Di	=U02W15V (Typ-Code/Stempel/marking)	35	Kec	→Z02W15V

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150	Si-P+N	=FC150(Typ-Code/Stempel/marking)	46	Say	→FC150
1501	Si-N	→ED1501	7a	-	-
1502	Si-N	→ED1502	7a	-	-
150A	Z-Di	=P6SMB150A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
150PH	Z-Di	=BZD23-C150(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
150PH	Z-Di	=BZD27-C150(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
151	Si-P	=FC151(Typ-Code/Stempel/marking)	46	Say	→FC151
152	Si-N	=FC152(Typ-Code/Stempel/marking)	46	Say	→FC152
154	Si-N+P	=FC154(Typ-Code/Stempel/marking)	46	Say	→FC154
155	Si-P+R	=FC155(Typ-Code/Stempel/marking)	46	Say	→FC155
156	Si-N	=FC156(Typ-Code/Stempel/marking)	46	Say	→FC156
157	Si-N	=FC157(Typ-Code/Stempel/marking)	46	Say	→FC157
15A	Z-Di	=1.5SMC15A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
15A	Z-Di	=MMBZ15VA(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
15A	Z-Di	=MMQA15V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
15A	Z-Di	=P6SMB15A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
15A	Z-Di	=PZM15NB2A(Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
15A	Si-Varistor	=VRYA15(Typ-Code/Stempel/marking)	?4-DIP	Shi	→VRYA15
15B	Z-Di	=HZF15BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF15BP
15C	Z-Di	=HZF15CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF15CP
15C	Z-Di	=MSCT15C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
15C	Z-Di	=P6SMB15CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
15D	Z-Di	=MMBZ15VD(Typ-Code/Stempel/marking)	35	Ons	→MMBZ15VD
15DF4..DF8	Si-Di	DF4=400V,DF6=600V,DF8=800V	-		-
15DF4..DF8	Si-Di	GI,S,400..800V,1,3A,150ns	31a	Inr	BYD33G..M,BYV960..E,RGP15G..M,+
15IP-02..10	Si-Di	Dual,50..1000V,15A	-	Gie	-
15L7	Z-Di	=KP15L07(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP15L07
15L8	Z-Di	=KP15L08(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP15L08
15N12	Z-Di	=KP15N12(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP15N12
15N14	Z-Di	=KP15N14(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP15N14
15PH	Z-Di	=BZD23-C15(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
15PH	Z-Di	=BZD27-C15(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
15R25	Z-Di	=KP15R25(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→KP15R25
15s	Si-Di	=BAS125-05W(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BAS125-05W
15SC4M	Si-Di	=DF15SC4M(Typ-Code/Stempel/marking)	30	Shi	→DF15SC4M
15SP-01..10	Si-Di	Dual,50..1000V,15A	-	Gie	-
15Y	Z-Di	=BZV49/C15(Typ-Code/Stempel/marking)	39	Val	→BZV49/C15
16	Si-Di	=1PS59SB16(Typ-Code/Stempel/marking)	35	Phi	→1PS59SB16
16	Si-Di	=BAS125-06(Typ-Code/Stempel/marking)	35	Sie	→BAS125-06
16	Z-Di	=MAZ5160(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZ5160
16	Si-N/P+R	=MUN5316DW1(Typ-Code/Stempel/marking	46	Ons	→MUN5316DW1
16	Z-Di	=U1Z16(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z16
16(X,Y,Z)	Z-Di	=U02W16V(Typ-Code/Stempel/marking)	35	Kec	→Z02W16V
16..S	Si-Di	=16SB..M:	32a$	-	-
1601	Si-P	→ED1601	7a	-	-
1602	Si-P	→ED1602	7a	-	-
16029	Si-N	?BD243C	-	Rca	→BD243C
16039	Si-N	?BD243C	-	Rca	→BD243C
16054P	Si-Di	?BA159	31a	Sgs	→BA159
16090	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16091	F-Thy	?S3702S	22a$	Rca	→S3702S
16092	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16093	Si-Di	?D2103S	34b&	Rca	→D2103S
16094	Si-Di	?D2103S	34b&	Rca	→D2103S
160A	Z-Di	=P6SMB160A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
160PH	Z-Di	=BZD23-C160(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
160PH	Z-Di	=BZD27-C160(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
16121	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16122	F-Thy	?S3702S	22a$	Rca	→S3702S
16123	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16152	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16157	F-Thy	?S3702S	22a$	Rca	→S3702S

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16159	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16207(B)	Si-N	?BD241A,B	17j$	Rca	→BD241A,B
16298	Si-N	?2N3055	-	Rca	→2N3055
16299	Si-N	?2N3055	-	Rca	→2N3055
16300	Si-N	?2N5296	-	Rca	→2N5296
16305	Si-N	?BD243C	17j$	Rca	→BD243C
16306	Si-P	?BD244C	17j$	Rca	→BD244C
16315	Si-N	?BD595	17j$	Rca	→BD595
16316	Si-P	?BD596	17j$	Rca	→BD596
16317	Si-N	?BD245A	18j$	Rca	→BD245A
16318	Si-P	?BD246A	18j$	Rca	→BD246A
16334	Si-N	?BD243B	-	Rca	→BD243B
16335	Si-N	?BD243B	-	Rca	→BD243B
16343	Si-P	?BD244C	-	Rca	→BD244C
163PH	Si-Di	=BYD163 (Typ-Code/Stempel/marking)	31	Phi	→BYD163
16410	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16411	F-Thy	?S3702S	22a$	Rca	→S3702S
16412	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16413	Si-Di	?D2103S	34b&	Rca	→D2103S
16420	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16421	F-Thy	?S3702S	22a$	Rca	→S3702S
16422	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16423	Si-Di	?D2103S	34b&	Rca	→D2103S
16443	F-Thy	?TIC106M	17h$	Rca	→TIC106M
16461	F-Thy	?S3702S	22a$	Rca	→S3702S
16476	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16477	F-Thy	?S3702S	22a$	Rca	→S3702S
16488	50Hz-Thy	?TAG626/600	17h$	Rca	→TAG626/600
16490	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16491	F-Thy	?S3702S	22a$	Rca	→S3702S
16492	Si-Di	?D2103SF	34b&	Rca	→D2103SF
16493	Si-Di	?D2103S	34b&	Rca	→D2103S
16503	Si-N	?2N3055	23a$	Rca	→2N3055
16562	Si-N	?2N5298	17j$	Rca	→2N5298
16563	Si-P	?2N6107	17j$	Rca	→2N6107
16585	Si-N	?BD943	-	Rca	→BD943
16586	Si-P	?BD944	-	Rca	→BD944
16606	Si-N	?BD809	17j$	Rca	→BD809
1664	Si-N	?2N3055	23a$	-	→2N3055
16640	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16641	F-Thy	?S3702S	22a$	Rca	→S3702S
16656	Si-N	?BU104	23a$	Rca	→BU104
16668	Si-N	?2N3055	23a$	Rca	→2N3055
16690	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16691	F-Thy	?S3702S	22a$	Rca	→S3702S
16810	Si-N	?BD607	17j$	Rca	→BD607
16811	Si-P	?BD608	17j$	Rca	→BD608
16837	50Hz-Thy	?2N4101	22a$	Rca	→2N4101
1685	Interface-IC	Failsafe Differential RS-422/RS-485 Bus Transceiver (52Mb/s)	1685	-	RS485,RS422
16888	F-Thy	?S3703SF	22a$	Rca	→S3703SF
16889	F-Thy	?S3702S	22a$	Rca	→S3702S
16924	Si-P	?BD810	17j$	Rca	→BD810
16A	Z-Di	=1.5SMC16A (Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
16A	Z-Di	=P6SMB16A (Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
16B	Z-Di	=HZF16BP (Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF16BP
16C	Z-Di	=HZF16CP (Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF16CP
16C	Z-Di	=P6SMB16CA (Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
16CL2C41A	Si-Di	Dual,L,S,150V,16A,<35ns	18p$	Tos	BYV72-150,BYW99P-150
16CL2CZ41A	Si-Di	=16CL2C41A: Iso	17p	-	BYQ30EX-150
16DL2C41A	Si-Di	Dual,L,S,200V,16A,<35ns	18p$	Tos	BYV72-200,BYV74-300
16DL2CZ41A	Si-Di	=16DL2C41A: Iso	17p	-	BYQ30EX-200
16DL2CZ47A	Si-Di	Dual,L,S,200V,16A,<35ns	17p	Tos	BYQ30EX-200
16FL2C41A	Si-Di	Dual,L,S,300V,16A,<35ns	18p$	Tos	-

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16FL2CZ41A	Si-Di	=16FL2C41A:Iso	17p	-	-
16FL2CZ47A	Si-Di	Dual,L,S,300V,16A,<35ns	17p	Tos	-
16FWJ2C42	Si-Di	Dual,Schottky,L,S,30V,16A(Tc=110o)	18p$	Tos	(BYS28-45,BYV73-40,MBR3045PT)
16FWJ2C42	Si-Di	Uf<0,55V(8A),<35ns	-		-
16GWJ2CZ47	Si-Di	Dual,Schottky,L,S,40V,16A	17p	Tos	BYV33F-40,BY133F-40
16N03L	MOS-N-FET-e	=RFD16N03L(Typ-Code/Stempel/marking)	30	Rca	→RFD16N03L
16PH	Z-Di	=BZD23-C16(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
16PH	Z-Di	=BZD27-C16(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
16s	Si-Di	=BAS125-06W(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BAS125-06W
16SB03M	Si-Di	Schottky,L,S,30V,15A(Tc=95o)	16f	Nec	-
16SB04M	Si-Di	=16SB03M:40V	16f	-	-
16Y	Z-Di	=BZV49/C16(Typ-Code/Stempel/marking)	39	Val	→BZV49/C16
17	Si-Di	=BAS125-07(Typ-Code/Stempel/marking)	44	Sie	→BAS125-07
1701	Si-N	→ED1701	7a	-	-
17018	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17019	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
1702	Si-N	→ED1702	7a	-	-
17020	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17021	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17022	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17023	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17024	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17025	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17026	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17027	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17028	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17029	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17030	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17031	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17032	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17033	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17034	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17035	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17036	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17037	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17040	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17041	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17052	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17053	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17054	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17055	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17056	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17057	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17058	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17058F	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17059	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17062	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17063	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17065	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17066	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17074	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17075	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17076	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17077	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17078	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17079	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17080	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17086	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17087	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
17088	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
17089	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
170A	Z-Di	=P6SMB170A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
17106	Thy	?17127	17h$	Rca	→17127

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17120	Thy	~17127	22a$	Rca	→17127
17122	Thy	~17127	17h$	Rca	→17127
17124	Thy	?17127	17h$	Rca	→17127
17126	Thy	~17127	22a$	Rca	→17127
17127	Thy	-	17h$	Rca	BStC1233S11
17132	Thy	~17127	17h$	Rca	→17127
17150	Thy	~17127	17h$	Rca	→17127
17154	Thy	?17127	17h$	Rca	→17127
17166	F-Thy+Di	→17088..89	17j$	Rca	17088,17089
17322	SI-N	?BD203	17j$	Rca	→BD203
17323	Si-P	?BD204	17j$	Rca	→BD204
17375	SI-N	?BD243C	17j$	Rca	→BD243C
17389	Si-N	?BD317	23a$	Rca	→BD317
17390	Si-P	?BD318	23a$	Rca	→BD318
17391	Si-N	?BD317	23a$	Rca	→BD317
174,180,185,203	SAW-Filter	(surface acoustic wave)	-		-
17484	Si-P	?BD544	-	Rca	→BD544
17520	Si-P-Darl	=TIP135	17j$	Rca	→TIP135
17521	Si-N-Darl	=TIP130	17j$	Rca	→TIP130
17560	Si-P	=RCA8638C	23a$	Rca	→RCA8638C
17561	SI-N	=RCA9116C	23a$	Rca	→RCA9116C
17597	SI-N	?BD243C	17j$	Rca	→BD243C
179	Si-N	=FMMT5179(Typ-Code/Stempel/marking)	35	Ztx	→FMMT5179
17DPH	SI-Di	=BYD17D(Typ-Code/Stempel/marking)	72	Phi	→BYD17..
17GPH	Si-Di	=BYD17G(Typ-Code/Stempel/marking)	72	Phi	→BYD17..
17JPH	Si-Di	=BYD17J(Typ-Code/Stempel/marking)	72	Phi	→BYD17..
17KPH	Si-Di	=BYD17K(Typ-Code/Stempel/marking)	72	Phi	→BYD17..
17MPH	Si-Di	=BYD17M(Typ-Code/Stempel/marking)	72	Phi	→BYD17..
17s	Si-Di	=BAS125-07W(Typ-Code/Stempel/marking)	44(2mm)	Sie	→BAS125-07W
18	Si-N	=BFP181T(Typ-Code/Stempel/marking)	44	Aeg	→BFP181T
18	Si-N+N-FET	=FC18(Typ-Code/Stempel/marking)	45	Say	→FC18
18	Z-Di	=MAZS180(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS180
18	Z-Di	=MM3Z33V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
18	Si-N+R	=PDTC143ZK(Typ-Code/Stempel/marking)	35(2mm)	Phl	→PDTC143ZK
18	N-FET	=SST108(Typ-Code/Stempel/marking)	35	Six	→SST108
18	Z-Di	=U1Z18(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z18
18(X,Y,Z)	Z-Di	=U02W18V(Typ-Code/Stempel/marking)	35	Kec	→Z02W18V
1801	Si-P	→ED1801	7a	-	-
1802	Si-P	→ED1802	7a	-	-
18022	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
18052	F-Thy+Di	?S3900S	17j$	Rca	→S3900S
18053	F-Thy+Di	?S3901S	17j$	Rca	→S3901S
180A	Z-Di	=P6SMB180A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
180PH	Z-Di	=BZD23-C180(Typ-Code/Stempel/marking)	31	Phl	→BZD23-C..
180PH	Z-Di	=BZD27-C180(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
180T2	Si-N	=BDY23	23a$	Tho	→BDY23
181	Si-N	=BFQ181(Typ-Code/Stempel/marking)	51	Sie	→BFQ181
181T2	Si-N	=BDY24	23a$	Tho	→BDY24
182	Si-N	=BFQ182(Typ-Code/Stempel/marking)	51	Sie	→BFQ182
182T2	Si-N	=BDY25	23a$	Tho	→BDY25
183T2	Si-N	=BDY26	23a$	Tho	→BDY26
184T2	Si-N	=BDY27	23a$	Tho	→BDY27
185T2	Si-N	=BDY28	23a$	Tho	→BDY28
18A	Z-Di	=1.5SMC18A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
18A	Z-Di	=MMBZ18VA(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
18A	Z-Di	=MMBZ5221B(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5221B
18A	Z-Di	=MMQA18V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
18A	Z-Di	=P6SMB18A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
18B	Z-Di	=HZF18BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF18BP
18B	Z-Di	=MMBZ5222B(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5222B
18C	Z-Di	=HZF18CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF18CP

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18C	Z-Di	=MMBZ5223B(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5223B
18C	Z-Di	=P6SMB18CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
18D	Z-Di	=MMBZ5224B(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5224B
18E	Z-Di	=MMBZ5225B(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5225B
18PH	Z-Di	=BZD23-C18(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
18PH	Z-Di	=BZD27-C18(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
18Y	Z-Di	=BZV49/C18(Typ-Code/Stempel/marking)	39	Val	→BZV49/C18
19	Z-Di	=MM3Z36V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
19	Si-P+R	=PDTA143ZK(Typ-Code/Stempel/marking)	35	Phi	→PDTA143ZK
19	N-FET	=SST109(Typ-Code/Stempel/marking)	35	Six	→SST109
193	Si-N	=BFP193T(Typ-Code/Stempel/marking)	44	Aeg	→BFP193
193DT2	Si-N	NF/S-L,210V,10A,85W,>5MHz	23a$	Tho	BD245F,2SC1586,2SD552,2SD583,+
194	Si-P	=BFQ194(Typ-Code/Stempel/marking)	51	Sie	→BFQ194
194	Si-P	=BFR194T(Typ-Code/Stempel/marking)	35	Aeg	→BFR194T
196	Si-N	=BFQ196(Typ-Code/Stempel/marking)	51	Sie	→BFQ196
1A...1M					
1A	Si-P	=2SB779(Typ-Code/Stempel/marking)	35	Mat	→2SB779
1A	Si-N	=BC846A(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC846
1A	Si-N	=BC846AF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC846F
1A	Si-N	=BC846AT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC846T
1A	Si-N	=BC846AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC846W
1A	Si-N	=FMMT3904(Typ-Code/Stempel/marking)	35	Fer	→FMMT3904
1A	Si-N	=KST3904(Typ-Code/Stempel/marking)	35	Sam	→KST3904
1A	Si-Di	=MA110(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA110
1A	Z-Di	=MM3Z47V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1A	Si-N	=MMBT3904(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT3904
1A	Si-N	=SXT3904(Typ-Code/Stempel/marking)	39	Sie	→SXT3904
1A	Si-N	=YTS3904(Typ-Code/Stempel/marking)	35	Tos	→YTS3904
-1A	Si-N	=PMST3904(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST3904
1A-	Si-N	=BC846AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC846W
1AG	Si-N	=2SC3339-GR(Typ-Code/Stempel/marking)	35	Tos	→2SC3339
1AG	Si-N/P	=HN1B01F-GR(Typ-Code/Stempel/marking)	46	Tos	→HN1B01F
1AG	Si-N/P	=HN1B01FU-GR(Typ-Code/Stempel/marking)	46(2mm)	Tos	→HN1B01FU
1AL	Si-N	=2SC3339-BL(Typ-Code/Stempel/marking)	35	Tos	→2SC3339
1AM	Si-N	=MMBT3904(Typ-Code/Stempel/marking)	35	Mot	→MMBT3904
1AO	Si-N	=2SC3339-O(Typ-Code/Stempel/marking)	35	Tos	→2SC3339
1Ap	Si-N	=BC846A(Typ-Code/Stempel/marking)	35	Phi	→BC846
1AQ	Si-P	=2SB1584-Q(Typ-Code/Stempel/marking)	?35	Mat	→2SB1584
1AQ	Si-P	=2SB779-Q(Typ-Code/Stempel/marking)	35	Mat	→2SB779
1AR	Si-P	=2SB1584-R(Typ-Code/Stempel/marking)	?35	Mat	→2SB1584
1AR	Si-P	=2SB779-R(Typ-Code/Stempel/marking)	35	Mat	→2SB779
1AR	Si-N	=BC846AR(Typ-Code/Stempel/marking)	35	Sie,Val	→BC846R
1AS	Si-P	=2SB1584-S(Typ-Code/Stempel/marking)	?35	Mat	→2SB1584
1AS	Si-P	=2SB779-S(Typ-Code/Stempel/marking)	35	Mat	→2SB779
1As	Si-N	=BC846A(Typ-Code/Stempel/marking)	35	Sie	→BC846
1As	Si-N	=BC846AW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC846W
1AS027	Si-Di	=1AS029:800V	32	Tix	BYD14K..M,BYW55..56,2N5062,+
1AS029	Si-Di	contr.av.,1000V,1,5A	32	Tix	BUD14M,BYD34M,BYV96E,BYW56,+
1At	Si-N	=BC846A(Typ-Code/Stempel/marking)	35	Phi	→BC846
1At	Si-N	=BC846AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC846W
1AY	Si-N	=2SC3339-Y(Typ-Code/Stempel/marking)	35	Tos	→2SC3339
1AY	Si-N/P	=HN1B01FU-Y(Typ-Code/Stempel/marking)	46(2mm)	Tos	→HN1B01FU
1AY	Si-N/P	=HN1B01F-Y(Typ-Code/Stempel/marking)	46	Tos	→HN1B01F
1AZ6,8..330	Z-Di	Z,6,8..330V,10%,1W	31a	Tos	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1B	Si-N	=BC846B(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC846
1B	Si-N	=BC846BDW1(Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC846..DW1
1B	Si-N	=BC846BF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC846F
1B	Si-N	=BC846BT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC846T
1B	Si-N	=BC846BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC846W
1B	Si-N	=FMMT2222(Typ-Code/Stempel/marking)	35	Fer	→FMMT2222
1B	Si-N	=KST2222(Typ-Code/Stempel/marking)	35	Sam	→KST2222
1B	Si-Di	=MA111(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA111
1B	Si-N	=MMBT2222(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBT2222

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1B	Si-N	=NMT2222(Typ-Code/Stempel/marking)	46	Nsc	→NMT2222
1B	Si-N	=YTS2222(Typ-Code/Stempel/marking)	3S	Tos	→YTS2222
-1B	Si-N	=PMST2222(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→PMST2222
1B-	Si-N	=BC846BW(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→BC846W
1B2C1	Si-Di	Dual,Gl,100V,2A	12p	Tos	2xBY126..127,2xBY133..135,2x1N4002..07
1B2Z1	Si-Di	=1B2C1:	12q	-	2xBY126..127,2xBY133..135,2x1N4002..07
1B4B1	Si-Br	100V,1,5A	8w	Tos	B80C1500
1B4B41	Si-Br	100V,1A	33x1	Tos	B80C1000
1B4B42	Si-Br	100V,1A	?4-DIP	Tos	B80C1000(DIP)
1BG	Si-N	=2SC3340-GR(Typ-Code/Stempel/marking)	3S	Tos	→2SC3340
1BH62	Si-Di	Gl,Uni,100V,1A,<1,5?s	31a	Tos	BY126,BY135,BY226,1N4002..4007,+
1BL	Si-N	=2SC3340-BL(Typ-Code/Stempel/marking)	3S	Tos	→2SC3340
1BL3	Si-Di	=MBRS130L(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→MBRS130L
1BL41	Si-Di	Gl,S,100V,1A,<60ns	31a	Tos	BYV26B..E,EGP10B..F,FE1B..H
1BL42	Si-Di	Gl,S,100V,1A,<60ns	31a	Tos	BYV26B..E,EGP10B..F,FE1B..H
1Bp	Si-N	=BC846B(Typ-Code/Stempel/marking)	3S	Phi	→BC846
1BR	Si-N	=BC846BR(Typ-Code/Stempel/marking)	3S	Phi,Sie	→BC846R
1Bs	Si-N/P	=BC817UPN(Typ-Code/Stempel/marking)	46	Sie	→BC817UPN
1Bs	Si-N	=BC846B(Typ-Code/Stempel/marking)	3S	Sie	→BC846
1Bs	Si-N	=BC846BW(Typ-Code/Stempel/marking)	3S(2mm)	Sie	→BC846W
1Bt	Si-N	=BC846B(Typ-Code/Stempel/marking)	3S	Phi	→BC846
1Bt	Si-N	=BC846BW(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→BC846W
1BZ	Si-Di	=U1BZ41(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1BZ41
1BZ61	Si-Di	Gl,Uni,100V,1A	31a	Tos	BY126,BY135,BY226,1N4002..4007,+
1C	Si-N	=FMMT-A20(Typ-Code/Stempel/marking)	3S	Fer	→FMMT-A20
1C	Si-N	=KST20(Typ-Code/Stempel/marking)	3S	Sam	→KST20
1C	Si-Di	=MA112(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA112
1C	Z-Di	=MM3Z51V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1C	Si-N	=MMBTA20(Typ-Code/Stempel/marking)	3S	Mot,Sam	→MMBTA20
1CL	Si-N	=2SC4082-L(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4082
1CL41	Si-Di	Gl,S,150V,1A,<60ns	31a	Tos	BYV26B..E,EGP10C..F,FE1C..H
1CL42	Si-Di	Gl,S,150V,1A,<60ns	31a	Tos	BYV26B..E,EGP10C..F,FE1C..H
1CM	Si-N	=2SC4082-M(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4082
1CN	Si-N	=2SC4082-N(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4082
1CO	Si-N	=2SC3341-O(Typ-Code/Stempel/marking)	3S	Tos	→2SC3341
1CP	Si-N	=2SC4082-P(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4082
1Cp	PIN-Di	=BAP50-05(Typ-Code/Stempel/marking)	3S	Phi	→BAP50-05
1CQ	Si-N	=2SC4082-Q(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4082
1Cs	Si-N	=BC847S(Typ-Code/Stempel/marking)	46(2mm)	Sie	→BC847S
1CY	Si-N	=2SC3341-Y(Typ-Code/Stempel/marking)	3S	Tos	→2SC3341
1D	Si-N	=2SB1328(Typ-Code/Stempel/marking)	3S	Mat	→2SD1328
1D	Si-N	=BC846(Typ-Code/Stempel/marking)	3S	Phi	→BC846
1D	Si-N	=BC846W(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→BC846W
1D	Si-N	=KST42(Typ-Code/Stempel/marking)	3S	Sam	→KST42
1D	Si-Di	=MA113(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA113
1D	Z-Di	=MM3Z56V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1D	Si-N	=MMBTA42(Typ-Code/Stempel/marking)	3S	Mot,Nsc,Sam	→MMBTA42
1D	Si-N	=SXTA42(Typ-Code/Stempel/marking)	39	Sie	→SXTA42
-1D	Si-N	=PMSTA42(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→PMSTA42
1D-	Si-N	=BC846W(Typ-Code/Stempel/marking)	3S(2mm)	Phi	→BC846W
1D2C1	Si-Di	Dual,Gl,200V,2A	12p	Tos	2xBY126..127,2xBY134..135,2x1N4003..07
1D2Z1	Si-Di	=1D2C1:	12q	-	2xBY126..127,2xBY134..135,2x1N4003..07
1D4B1	Si-Br	200V,1,5A	8w	Tos	B150C1500
1D4B41	Si-Br	200V,1A	33x1	Tos	B150C1000
1D4B42	Si-Br	200V,1A	?4-DIP	Tos	B150C1000(DIP)
1DG	Si-N/P	=HN1B04FU-GR(Typ-Code/Stempel/marking)	46(2mm)	Tos	→HN1B04FU
1DH62	Si-Di	Gl,Uni,200V,1A,<1,5?s	31a	Tos	BY126,BY134,BY226,1N4003..4007,+
1DL	Si-N	=2SC4083-L(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4083
1DL41	Si-Di	Gl,S,200V,1A,<60ns	31a	Tos	BYV26B..E,EGP10D..F,FE1D..H
1DL42	Si-Di	Gl,S,200V,1A,<60ns	31a	Tos	BYV26B..E,EGP10D..F,FE1D..H
1DM	Si-N	=2SC4083-M(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4083
1DN	Si-N	=2SC4083-N(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4083
1DP	Si-N	=2SC4083-P(Typ-Code/Stempel/marking)	3S(2mm)	Rhm	→2SC4083
1Dp	Si-N	=BC846(Typ-Code/Stempel/marking)	3S	Phi	→BC846

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1DQ	Si-N	=2SC4083-Q(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4083
1DR	Si-N	=2SD1328-R(Typ-Code/Stempel/marking)	35	Mat	→2SD1328
1DR	Si-N	=2SD2436-R(Typ-Code/Stempel/marking)	?35	Mat	→2SD2436
1DS	Si-N	=2SD1328-S(Typ-Code/Stempel/marking)	35	Mat	→2SD1328
1DS	Si-N	=2SD2436-S(Typ-Code/Stempel/marking)	?35	Mat	→2SD2436
1Ds	Si-N	=BC846S(Typ-Code/Stempel/marking)	46(2mm)	Sie	→BC846S
1Ds	Si-N	=BC846U(Typ-Code/Stempel/marking)	46	Sie	→BC846U
1DT	Si-N	=2SD1328-T(Typ-Code/Stempel/marking)	35	Mat	→2SD1328
1DT	Si-N	=2SD2436-T(Typ-Code/Stempel/marking)	?35	Mat	→2SD2436
1Dt	Si-N	=BC846(Typ-Code/Stempel/marking)	35	Phi	→BC846
1Dt	Si-N	=BC846W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC846W
1DY	Si-N/P	=HN1B04FU-Y(Typ-Code/Stempel/marking)	46(2mm)	Tos	→HN1B04FU
1DZ	Si-Di	=U1DZ41(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1DZ41
1DZ61	Si-Di	GI,Uni,200V,1A	31a	Tos	BY126,BY134,BY226,1N4003..4007,+
1E	Si-N	=BC847A(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC847
1E	Si-N	=BC847AF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847F
1E	Si-N	=BC847AT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847T
1E	Si-N	=BC847AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1E	Si-N	=FMMT-A43(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A43
1E	Si-N	=KST43(Typ-Code/Stempel/marking)	35	Sam	→KST43
1E	Si-Di	=MA114(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA114
1E	Z-Di	=MM3Z62V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1E	Si-N	=MMBTA43(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBTA43
1E	Si-N	=SXTA43(Typ-Code/Stempel/marking)	39	Sie	→SXTA43
-1E	Si-N	=PMSTA43(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA43
1E-	Si-N	=BC847AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1EL	Si-N	=2SC4084-L(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4084
1EM	Si-N	=2SC4084-M(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4084
1EN	Si-N	=2SC4084-N(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4084
1EP	Si-N	=2SC4084-P(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4084
1Ep	Si-N	=BC847A(Typ-Code/Stempel/marking)	35	Phi	→BC847
1EQ	Si-N	=2SC4084-Q(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4084
1ER	Si-N	=BC847AR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC847R
1Es	Si-N	=BC847A(Typ-Code/Stempel/marking)	35	Sie	→BC847
1Es	Si-N	=BC847AW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC847W
1&t	Si-N	=BC847A(Typ-Code/Stempel/marking)	35	Phi	→BC847
1Et	Si-N	=BC847AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1EZ100..200D10	Z-Di	100..200V,1W,10%	31a	Sie	BZW22/..BZX61/..BZX85/..
1EZ100..200D5	Z-Di	100..200V,1W,5%	31a	Sie	BZW22/..BZX61/..BZX85/..
1EZ100..200D5,10	Z-Di	100..200V,1W,D5=5%,D10=10%	31a	Sie	BZW22/..,BZX61/..,BZX85/..,+
1F	Si-N	=2SC4543(Typ-Code/Stempel/marking)	39	Mat	→2SC4543
1F	Si-N	=BC847B(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC847
1F	Si-N	=BC847BDW1(Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC847..DW1
1F	Si-N	=BC847BF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847F
1F	Si-N	=BC847BT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847T
1F	Si-N	=BC847BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1F	Si-N	=KST5550(Typ-Code/Stempel/marking)	35	Sam	→KST5550
1F	Si-Di	=MA115(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA115
1F	Z-Di	=MM3Z68V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1F	Si-N	=MMBT5550(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT5550
1F	Si-Di	=U1FWJ44N(Typ-Code/Stempel/marking)	71(5x2,5)	Tos	→U1FWJ44N
-1F	Si-N	=PMST5550(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST5550
1F-	Si-N	=BC847BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1F106	Si-Di	Schottky-Di,S,15V,20mA	-	Fui	BAT19,BAT45,1SS106
1FP	N-FET	=2SK321-P(Typ-Code/Stempel/marking)	35	Mat	→2SK321
1Fp	Si-N	=BC847B(Typ-Code/Stempel/marking)	35	Phi	→BC847
1FQ	N-FET	=2SK321-Q(Typ-Code/Stempel/marking)	35	Mat	→2SK321
1FR	N-FET	=2SK321-R(Typ-Code/Stempel/marking)	35	Mat	→2SK321
1FR	Si-N	=BC847BR(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC847R
1FS	N-FET	=2SK321-S(Typ-Code/Stempel/marking)	35	Mat	→2SK321
1Fs	Si-N	=BC847B(Typ-Code/Stempel/marking)	35	Sie	→BC847
1Fs	Si-N	=BC847BW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC847W
1Ft	Si-N	=BC847B(Typ-Code/Stempel/marking)	35	Phi	→BC847
1Ft	Si-N	=BC847BS(Typ-Code/Stempel/marking)	46	Phi	→BC847BS

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1Ft	Si-N	=BC847BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1FWJ42	Si-Di	Schottky-Di, 30V, 1A, <35ns	31a	Tos	-
1FWJ43	Si-Di	Schottky-Di, 30V, 1A, <35ns	31a	Tos	-
1G	Si-N	=BC847C(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC847
1G	Si-N	=BC847CDW1(Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC847..DW1
1G	Si-N	=BC847CF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847F
1G	Si-N	=BC847CT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC847T
1G	Si-N	=BC847CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1G	Si-N	=FMMT-A06(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A06
1G	Si-N	=KST06(Typ-Code/Stempel/marking)	35	Sam	→KST06
1G	Z-Di	=MM3Z75V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
1G	Si-N	=MMBTA06(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBTA06
-1G	Si-N	=PMSTA06(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA06
1G-	Si-N	=BC847CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1G2C1	Si-Di	Dual, GI, 400V, 2A	12p	Tos	2xBY126..127,2xBY133..134,2x1N4004..07
1G2Z1	Si-Di	=1G2C1:	12q	-	2xBY126..127,2xBY133..134,2x1N4004..07
1G4B1	Si-Br	400V, 1,5A	8w	Tos	B250C1500
1G4B41	Si-Br	400V, 1A	33x1	Tos	B250C1000
1G4B42	Si-Br	400V, 1A	?4-DIP	Tos	B250C1000(DIP)
1GH62	Si-Di	GI, Uni, 400V, 1A, <1,5?s	31a	Tos	BY126, BY134, BY226, 1N4004..4007, +
1GM	Si-N	=MMBTA06(Typ-Code/Stempel/marking)	35	Mot	→MMBTA06
1GR	Si-N	=BC847CR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC847R
1Gs	Si-N	=BC847CW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC847W
1Gt	Si-N	=BC847C(Typ-Code/Stempel/marking)	35	Phi	→BC847
1Gt	Si-N	=BC847CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1GT	Si-N	=SOA06(Typ-Code/Stempel/marking)	35	Tho	→SOA06
1GWJ42	Si-Di	Schottky-Di, 40V, 1A, <35ns	31a	Tos	-
1GWJ43	Si-Di	Schottky-Di, 40V, 1A, <35ns	31a	Tos	-
1GZ	Si-Di	=U1GZ41(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1GZ41
1GZ61	Si-Di	GI, Uni, 400V, 1A	31a	Tos	BY126, BY134, BY226, 1N4004..4007, +
1H	Si-N	=2SD2185(Typ-Code/Stempel/marking)	39	Mat	→2SD2185
1H	N-FET	=2SK123(Typ-Code/Stempel/marking)	35	Mat	→2SK123
1H	N-FET	=2SK1860(Typ-Code/Stempel/marking)	?35	Mat	→2SK1860
1H	Si-N	=BC847(Typ-Code/Stempel/marking)	35	Phi	→BC847
1H	Si-N	=BC847W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1H	Si-N	=FMMT-A05(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A05
1H	Si-N	=KST05(Typ-Code/Stempel/marking)	35	Sam	→KST05
1H	Si-Di	=MA116(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA116
1H	Si-N	=MMBTA05(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBTA05
-1H	Si-N	=PMSTA05(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA05
1H-	Si-N	=BC847W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1Hp	Si-N	=BC847(Typ-Code/Stempel/marking)	35	Phi	→BC847
1HR	Si-N	=2SD2185-R(Typ-Code/Stempel/marking)	39	Mat	→2SD2185
1HS	Si-N	=2SD2185-S(Typ-Code/Stempel/marking)	39	Mat	→2SD2185
1Ht	Si-N	=BC847(Typ-Code/Stempel/marking)	35	Phi	→BC847
1Ht	Si-N	=BC847W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC847W
1HT	Si-N	=SOA05(Typ-Code/Stempel/marking)	35	Tho	→SOA05
1I	Si-P	=2SB1440(Typ-Code/Stempel/marking)	39	Mat	→2SB1440
1IR	Si-P	=2SB1440-R(Typ-Code/Stempel/marking)	39	Mat	→2SB1440
1IS	Si-P	=2SB1440-S(Typ-Code/Stempel/marking)	39	Mat	→2SB1440
1J	Si-N	=BC848A(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC848
1J	Si-N	=BC848AF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848F
1J	Si-N	=BC848AT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848T
1J	SI-N	=BC848AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1J	Si-N	=FMMT2369(Typ-Code/Stempel/marking)	35	Fer	→FMMT2369
1J	Si-N	=MMBT2369(Typ-Code/Stempel/marking)	35	Mot	→MMBT2369
-1J	Si-N	=PMST2369(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST2369
1J2	Si-Di	=SS1J2(Typ-Code/Stempel/marking)	31	Org	→SS1J2
1J2C1	Si-Di	Dual, GI, 600V, 2A	12p	Tos	2xBY126..127,2xBY133..134,2x1N4005..07
1J2Z1	Si-Di	=1J2C1:	12q	-	2xBY126..127,2xBY133..134,2x1N4005..07
1J4	Si-Di	=SS1J4(Typ-Code/Stempel/marking)	31	Org	→SS1J4
1J4B1	Si-Br	600V, 1,5A	8w	Tos	B380C1500
1J4B41	SI-Br	400V, 1A	33x1	Tos	B250C1000
1J4B42	Si-Br	600V, 1A	?4-DIP	Tos	B500C1000(DIP)

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1J6	Si-Di	=SS1J6(Typ-Code/Stempel/marking)	31	Org	→SS1J6
1JA	Si-N	=MMBT2369A(Typ-Code/Stempel/marking)	35	Mot	→MMBT2369A
1JH62	Si-Di	GI,Uni,600V,1A,<1,5?s	31a	Tos	BY126,BY134,BY226,1N4005..4007,+
1Jp	Si-N	=BC848A(Typ-Code/Stempel/marking)	35	Phi	→BC848
1Jp	Si-N	=BCV61A(Typ-Code/Stempel/marking)	44	Phi	→BCV61
1JR	Si-N	=BC848AR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC848R
1Js	Si-N	=BC848A(Typ-Code/Stempel/marking)	35	Sie	→BC848
1Js	Si-N	=BC848AW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC848W
1Js	Si-N	=BCV61A(Typ-Code/Stempel/marking)	44	Sie	→BCV61
1Jt	Si-N	=BC848AW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1JZ	Si-Di	=U1JZ41(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1JZ41
1JZ61	Si-Di	GI,Uni,600V,1A	31a	Tos	BY126,BY134,BY226,1N4005..4007,+
1K	Si-N	=BC848B(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC848
1K	Si-N	=BC848BDW1(Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC848..DW1
1K	Si-N	=BC848BF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848F
1K	Si-N	=BC848BT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848T
1K	Si-N	=BC848BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1K	Si-N	=KST6428(Typ-Code/Stempel/marking)	35	Sam	→KST6428
1K	Si-N	=MMBT6428(Typ-Code/Stempel/marking)	35	Mot	→MMBT6428
-1K	Si-N	=PMST6428(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST6428
1K34(A)	Ge-Di	?1N34	31a	-	→1N34
1K60	Ge-Di	?1N60	31a	-	→1N60
1K90	Ge-Di	?1N90	31a	-	→1N90
1KM	Si-N	=MMBT6428(Typ-Code/Stempel/marking)	35	Mot	→MMBT6428
1KP	N-FET	=2SK316-P(Typ-Code/Stempel/marking)	35	Mat	→2SK316
1Kp	Si-N	=BCV61B(Typ-Code/Stempel/marking)	44	Phi	→BCV61
1KQ	N-FET	=2SK316-Q(Typ-Code/Stempel/marking)	35	Mat	→2SK316
1KR	Si-N	=2SD2210-R(Typ-Code/Stempel/marking)	39	Mat	→2SD2210
1KR	Si-N	=BC848BR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC848R
1KS	Si-N	=2SD2210-S(Typ-Code/Stempel/marking)	39	Mat	→2SD2210
1Ks	Si-N	=BC848BW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC848W
1Ks	Si-N	=BCV61B(Typ-Code/Stempel/marking)	44	Sie	→BCV61
1KT	Si-N	=2SD2210-T(Typ-Code/Stempel/marking)	39	Mat	→2SD2210
1Kt	Si-N	=BC848BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1L	Si-P	=2SB1537(Typ-Code/Stempel/marking)	39	Mat	→2SB1537
1L	Si-N	=BC848C(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC848
1L	Si-N	=BC848CDW1(Typ-Code/Stempel/marking)	46(2mm)	Ons	→BC848..DW1
1L	Si-N	=BC848CF(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848F
1L	Si-N	=BC848CT(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→BC848T
1L	Si-N	=BC848CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1L	Si-N	=MMBT6429(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBT6429
-1L	Si-N	=PMST6429(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST6429
1LB311	TTLLogic	HVcc:(5.0n0.25)Vtpd=7ns	14dil	Sov	2x4NAND 7420a
1LB312	TTLLogic	HVcc:(5.0n0.25)Vtpd=9ns	14dil	Sov	1x8NAND 7430a
1LB316	TTLLogic	HVcc:(5.0n0.25)Vtpd=5ns	14dil	Sov	2x4NAND(FQ=30) 7440a
1LB551	TTLLogic	NVcc:(5.0n0.25)Vtpd=12.5ns	14dil	Sov	2x4NAND 7420a
1LB552	TTLLogic	NVcc:(5.0n0.25)Vtpd=12.5ns	14dil	Sov	1x8NAND 7430a
1LB553	TTLLogic	NVcc:(5.0n0.25)Vtpd=10ns	14dil	Sov	4x2NAND 7400a
1LB554	TTLLogic	NVcc:(5.0n0.25)Vtpd=12.5ns	14dil	Sov	3x3NAND 7410a
1LB556	TTLLogic	NVcc:(5.0n0.25)Vtpd=10ns	14dil	Sov	2x4NAND(FQ=30) 7440a
1LB558	TTLLogic	NVcc:(5.0n0.25)Vtpd=8.5ns	14dil	Sov	4x2NAND 7403
1LB581	TTLLogic	LVcc:(5.0n0.25)Vtpd<45ns	14dil	Gus	2x4NAND 7420a
1LE11	Si-Di	GI,contr.av.,800V,1A,Pbr=1kW(10?s)	34a$	Tos	BYD13K..M,BYW55..56,1N4248..49,+
1LH62	Si-Di	GI,Uni,800V,1A,<1,5?s	31a	Tos	BY126,BY133,BY227,1N4006..4007,+
1LM	Si-N	=2SC4103-M(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4103
1LN	Si-N	=2SC4103-N(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4103
1LP	Si-N	=2SC4103-P(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4103
1Lp	Si-N	=BC848C(Typ-Code/Stempel/marking)	35	Phi	→BC848
1Lp	Si-N	=BCV61C(Typ-Code/Stempel/marking)	44	Phi	→BCV61
1LP551	TTLLogic	NVcc:(5.0n0.25)Vtpd=11ns	14dil	Sov	2x4ANDExp 7460a
1LQ	Si-N	=2SC4103-Q(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4103
1LR	Si-N	=BC848CR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC848R
1LR551	TTLLogic	NVcc:(5.0n0.25)Vtpd=9ns	14dil	Sov	Dual2x2AND/NOR,exp 7450a
1LR553	TTLLogic	NVcc:(5.0n0.25)Vtpd=9ns	14dil	Sov	4x2AND/NOR,exp 7453a

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1Ls	Si-N	=BC848C(Typ-Code/Stempel/marking)	35	Sie	→BC848
1Ls	Si-N	=BC848CW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC848W
1Ls	Si-N	=BCV61C(Typ-Code/Stempel/marking)	44	Sie	→BCV61
1Lt	Si-N	=BC848CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1LZ61	Si-Di	GI,Uni,800V,1A	31a	Tos	BY126,BY133,BY227,1N4006..4007,+
1M	Si-N	=2SD2357(Typ-Code/Stempel/marking)	39	Mat	→2SD2357
1M	Si-N	=BC848(Typ-Code/Stempel/marking)	35	Phi	→BC848
1M	Si-N	=BC848W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1M	Si-N	=FMMT-A13(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A13
1M	Si-N	=IMBT3903(Typ-Code/Stempel/marking)	35	Itt	→IMBT3903
1M	Si-N	=KST13(Typ-Code/Stempel/marking)	35	Sam	→KST13
1M	Si-N	=MMBTA13(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBTA13
1M...ZS10	Z-Di	n10%	31a	-	BZD23/..,BZT03/..,BZX70/..
1M...ZS5	Z-Di	n5%	31a	-	BZD23/..,BZT03/..,BZX70/..
1M3.3..200ZS	Z-Di	3,3..200V,2,5W,n20%	31a	Mot	BZD23/..,BZT03/..,BZX70/..
1MB03D-120	MOS-N-IGBT	L,int.Free-wheelDi,1200V,5A,70W	18id	Fjd	-
1MB05-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,9A,100W	18id	Fjd	GN12015C,GT15Q101
1MB05D-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,9A,100W	18id	Fjd	-
1MB08-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,13A,115W	18id	Fjd	GN12015C,GT15Q101
1MB08D-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,13A,115W	18id	Fjd	MGW12N120D
1MB10-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,16A,135W	18id	Fjd	MGW12N120
1MB10D-120	MOS-N-IGBT	L,Int.Free-wheelDi,1200V,16A,135W	18id	Fjd	MGW12N120D
1MB15D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,33A,120W	18id	Fjd	BUP602D
1MB20-060	MOS-N-IGBT	L,600V,38A,145W,1,8/1,35?s	18id	Fjd	-
1MB20D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,38A,145W	18id	Fjd	BUP603D
1MB30-060	MOS-N-IGBT	L,600V,48A,180W,1,8/1,35?s	18id	Fjd	MGW30N60
1MBC03-120	MOS-N-IGBT	L,1200V,5A,70W,<1,8/2?s	17id	Fjd	-
1MBC05-060	MOS-N-IGBT	L,600V,13A,50W,<1,8/1,35?s	17id	Fjd	GN6015A
1MBC05D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,13A,50W	17id	Fjd	BUP410D
1MBC10-060	MOS-N-IGBT	L,600V,20A,75W,<1,8/1,35?s	17id	Fjd	BUP400
1MBC10D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,20A,75W	17id	Fjd	BUP400D
1MBC15-060	MOS-N-IGBT	L,600V,24A,90W,<1,8/1,35?s	17id	Fjd	BUP401
1MBG05D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,13A,50W	30id	Fjd	-
1MBG10D-060	MOS-N-IGBT	L,Int.Free-wheelDi,600V,20A,75W	30id	Fjd	-
1MBH15-120	MOS-N-IGBT	L,1200V,26A,245W,1,8/2?s	77id	Fjd	GT25Q101
1MBH15D-120	MOS-N-IGBT	L,int.Free-wheelDi,1200V,26A,245W	77id	Fjd	MGY20N120D
1MBH25-120	MOS-N-IGBT	L,1200V,38A,310W,1,8/2?s	77id	Fjd	-
1MBH25D-120	MOS-N-IGBT	L,int.Free-wheelDi,1200V,38A,310W	77id	Fjd	-
1MBH30D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,58A,220W	77id	Fjd	MGY40N60D
1MBH50-060	MOS-N-IGBT	L,600V,82A,310W,1,8/1,35?s	77id	Fjd	-
1MBH50D-060	MOS-N-IGBT	L,int.Free-wheelDi,600V,82A,310W	77id	Fjd	-
1MN	Si-N	=2SC4128-N(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC4128
1MP	Si-N	=2SC4128-P(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC4128
1MP	Si-P	=2SJ84-P(Typ-Code/Stempel/marking)	35	Mat	→2SJ84
1Mp	Si-N	=BC848(Typ-Code/Stempel/marking)	35	Phi	→BC848
1Mp	Si-N	=BCV61(Typ-Code/Stempel/marking)	44	Phi	→BCV61
1MQ	Si-P	=2SJ84-Q(Typ-Code/Stempel/marking)	35	Mat	→2SJ84
1MR	Si-P	=2SJ84-R(Typ-Code/Stempel/marking)	35	Mat	→2SJ84
1Mt	Si-N	=BC848W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC848W
1N					
1N	Si-P	=2SB1539(Typ-Code/Stempel/marking)	39	Mat	→2SB1539
1N	Si-N	=FMMT-A14(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A14
1N	Si-N	=IMBT3904(Typ-Code/Stempel/marking)	35	Itt	→IMBT3904
1N	Si-N	=KST14(Typ-Code/Stempel/marking)	35	Sam	→KST14
1N	Si-N	=MMBTA14(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBTA14
1N10..	MOS-N-FET-e	=MMFT1N10E(Typ-Code/Stempel/marking)	48	Mot	→MMFT1N10E
1N100(A)	Ge-Di	Uni,100V,30mA,A:70mA	31a	USA,Tho	AA117..118,AA132..133
1N1005	Ge-Di	GI,380V,0,25A	-		-
1N1007	Ge-Di	GI,380V,0,35A	-		-
1N1008	Ge-Di	GI,380V,0,4A	-		-
1N101	Ge-Di	Uni,150V,10mA	-		AA133,1N39
1N1013	Ge-Di	GI,380V,0,25A	-		-
1N1016	Ge-Di	GI,380V,0,4A	-		-

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1N102	Ge-Di	Uni,125V	31a	USA	AA133,1N39
1N1021	Ge-Di	GI,380V,0,25A	-		-
1N1022	Ge-Di	GI,380V,0,3A	-		-
1N1023	Ge-Di	GI,380V,0,35A	-		-
1N1024	Ge-Di	GI,380V,0,4A	-		-
1N1028	Si-Di	GI,50V,0,5A(Ta=100o)	?34a	USA	BY126..127,BY133..135,1N4001..07,+
1N1029	Si-Di	=1N1028:100V	?34a	-	BY126..127,BY133..135,1N4002..07,+
1N103	Ge-Di	Uni,20V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1030	Si-Di	=1N1028:150V	?34a	-	BY126..127,BY133..135,1N4003..07,+
1N1031	Si-Di	=1N1028:200V	?34a	-	BY126..127,BY133..134,1N4003..07,+
1N1032	Si-Di	=1N1028:300V	?34a	-	BY126..127,BY133..134,1N4004..07,+
1N1033	Si-Di	=1N1028:400V	?34a	-	BY126..127,BY133..134,1N4004..07,+
1N1034	Si-Di	GI-L,50V,1A(Tc=100o)	?32b	USA	BYX38/300R,BYX39/600R
1N1035	Si-Di	=1N1034:100V	?32b	-	BYX38/300R,BYX39/600R
1N1036	Si-Di	=1N1034:150V	?32b	-	BYX38/300R,BYX39/600R
1N1037	Si-Di	=1N1034:200V	?32b	-	BYX38/300R,BYX39/600R
1N1038	Si-Di	=1N1034:300V	?32b	-	BYX38/300R,BYX39/600R
1N1039	Si-Di	=1N1034:400V	?32b	-	BYX38/600R,BYX39/600R
1N104	Ge-Di	Uni,25V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1040	Si-Di	GI,50V,1A(Tc=100o)	?32b	USA	BYX38/300R,BYX39/600R
1N1041	Si-Di	=1N1040:100V	?32b	-	BYX38/300R,BYX39/600R
1N1042	Si-Di	=1N1040:150V	?32b	-	BYX38/300R,BYX39/600R
1N1043	Si-Di	=1N1040:200V	?32b	-	BYX38/300R,BYX39/600R
1N1044	Si-Di	=1N1040:300V	?32b	-	BYX38/300R,BYX39/600R
1N1045	Si-Di	=1N1040:400V	?32b	-	BYX38/600R,BYX39/600R
1N1046	Si-Di	GI,50V,1A(Tc=100o)	-	USA	-
1N1047	Si-Di	=1N1046:100V	-		-
1N1048	Si-Di	=1N1046:150V	-		-
1N1049	Si-Di	=1N1046:200V	-		-
1N105	Di	UHF,25V	-	Kem	-
1N1050	Si-Di	=1N1046:300V	-		-
1N1051	Si-Di	=1N1046:400V	-		-
1N1052	Si-Di	GI,50V,1,5A(Tc=100o)	?34a	USA	BYW52..56,BYX82..87.1N5391..97,+
1N1053	Si-Di	=1N1052:100V	?34a	-	BYW52..56,BYX82..87.1N5392..97,+
1N1054	Si-Di	=1N1052:150V	?34a	-	BYW52..56,BYX82..87.1N5393..97,+
1N1055	Si-Di	=1N1052:200V	?34a	-	BYW52..56,BYX82..87.1N5393..97,+
1N1056	Si-Di	=1N1052:300V	?34a	-	BYW53..56,BYX83..87.1N5394..97,+
1N1057	Si-Di	=1N1052:400V	?34a	-	BYW53..56,BYX83..87.1N5395..97,+
1N1058	Si-Di	GI,50V,5A(Tc=100o)	32b&	USA	BYX38/300R,BYX39/600R
1N1059	Si-Di	=1N1058:100V	32b&	-	BYX38/300R,BYX39/600R
1N106	Ge-Di	Uni,300V	31a	-	-
1N1060	Si-Di	=1N1058:150V	32b&	-	BYX38/300R,BYX39/600R
1N1061	Si-Di	=1N1058:200V	32b&	-	BYX38/300R,BYX39/600R
1N1062	Si-Di	=1N1058:300V	32b&	-	BYX38/300R,BYX39/600R
1N1063	Si-Di	=1N1058:400V	32b&	-	BYX38/600R,BYX39/600R
1N1064	Si-Di	GI-L,50V,5A(Tc=100o)	32b&	USA	BYX38/300R,BYX39/600R
1N1065	Si-Di	=1N1064:100V	32b&	-	BYX38/300R,BYX39/600R
1N1066	Si-Di	=1N1064:150V	32b&	-	BYX38/300R,BYX39/600R
1N1067	Si-Di	=1N1064:200V	32b&	-	BYX38/300R,BYX39/600R
1N1068	Si-Di	=1N1064:300V	32b&	-	BYX38/300R,BYX39/600R
1N1069	Si-Di	=1N1064:400V	32b&	-	BYX38/600R,BYX39/600R
1N107	Ge-Di	Uni,10V,100mA	31a	USA	AA135..136,AA139
1N1070	Si-Di	GI-L,50V,5A(Tc=100o)	-	USA	-
1N1071	Si-Di	=2N1070:100V	-		-
1N1072	Si-Di	=2N1070:150V	-		-
1N1073	Si-Di	=2N1070:200V	-		-
1N1074	Si-Di	=2N1070:300V	-		-
1N1075	Si-Di	=2N1070:400V	-		-
1N1076	Si-Di	GI-L,50V,15A(Tc=100o)	-	USA	-
1N1077	Si-Di	=1N1076:100V	-		-
1N1078	Si-Di	=1N1076:150V	-		-
1N1079	Si-Di	=1N1076:200V	-		-
1N108	Ge-Di	Uni,50V	31a	USA	AA135..136,AA139
1N1080	Si-Di	=1N1076:300V	-		-

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1N1081(A)	Si-Di	Gl,100V,0,5..0,75A(Ta=100o)	-	USA	BY126..127,BY133..135,1N4002..07,+
1N1082(A)	Si-Di	=1N1081(A):200V	-		BY126..127,BY133..134,1N4003..07,+
1N1083(A)	Si-Di	=1N1081(A):300V	-		BY126..127,BY133..134,1N4004..07,+
1N1084(A)	Si-Di	=1N1081(A):400V	-		BY126..127,BY133..134,1N4004..07,+
1N1085(A)	Si-Di	Gl,100V,1,5..2A(Ta=100o)	-	USA	BY251..255,BYW52..56,1N5060..62,+
1N1086(A)	SI-Di	=1N1085:200V	-		BY251..255,BYW52..56,1N5060..62,+
1N1087(A)	Si-Di	=1N1085:300V	-		BY252..255,BYW53..56,1N5060..62,+
1N1088(A)	Si-Di	=1N1085:400V	-		BY252..255,BYW53..56,1N5060..62,+
1N1089(A)	SI-Di	Gl,100V,5A(Ta=100o)	-	USA	BY214/100,MR751..760
1N109	Ge-Di	0,15V,50mA	31a	Kem	-
1N1090(A)	Si-Di	=1N1089:200V	-		BY214/200,MR752..760
1N1091(A)	Si-Di	=1N1089:300V	-		BY214/400,MR754..760
1N1092(A)	Si-Di	=1N1089:400V	-		BY214/400,MR754..760
1N1093	Ge-Di	S,15V,500ns	31a	USA	AAY27..28,1N191..192,1N3592
1N1095	Si-Di	Gl,500V,0,75A(Tc=50o)	34a	Rca,Tix,++	BY126..127.BY133..134,1N4005..07,+
1N1096	Si-Di	=1N1095:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N110	Ge-Di	UHF-M	Koax	Gie	-
1N1100	Si-Di	Gl,100V,0,75A(Tc=50o)	34a	USA	BY126..127,BY133..135,1N4002..07,+
1N1101	Si-Di	=1N1100:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1102	SI-Di	=1N1100:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1103	Si-Di	=1N1100:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1104	Si-Di	=1N1100:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1105	Si-Di	=1N1100:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1108	Si-Di	Gl,800V,0,45A	-	USA	BA158..159,BY127,BY133,BY268,+
1N1109	Si-Di	Gl,1200V,0,43A	-	USA	BY127,BY133,BY268..269,+
1N111	Ge-Di	Gl,S,70V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1110	Si-Di	Gl,1600V,0,4A	-	USA	BY269,BY400,DM513,EM516,GP10Y
1N1111	Si-Di	Gl,2000V,0,38A	-	USA	1N1732A..1734A
1N1112	Si-Di	Gl,2400V,0,35A	-	USA	1N1733A..1734A
1N1113	Si-Di	Gl,2800V,0,33A	-	USA	1N1733A..1734A
1N1115	Si-Di	Gl,100V,1,5A(Tc=85o)	32a$	USA,Tix	BYX38/300,BYX39/600
1N1115R...1120R	Si-Di	=1N1115..1120:	32b&	-	BYX38/600R,BYX39/600R
1N1115R..1120R	Si-Di	=1N1115..1120:Reverse	32b&	-	BYX38/600R,BYX39/600R
1N1116	Si-Di	=1N1115:200V	32a$	-	BYX38/300,BYX39/600
1N1117	Si-Di	=1N1115:300V	32a$	-	BYX38/300,BYX39/600
1N1118	Si-Di	=1N1115:400V	32a$	-	BYX38/600,BYX39/600
1N1119	Si-Di	=1N1115:500V	32a$	-	BYX38/600,BYX39/600
1N112	Ge-Di	Gl,S,70V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1120	Si-Di	=1N1115:600V	32a$	-	BYX38/600,BYX39/600
1N1124(A)	Si-Di	Gl-L,200V,3..3,3A(Tc=50o)	32a$	USA,Tix	BYX38/600,BYX39/600
1N1124R...1128R	Si-Di	=1N1124(A)..1128(A):	32b&	-	BYX38/600R,BYX39/600R
1N1125(A)	Si-Di	=1N1124(A):300V	32a$	-	BYX38/600,BYX39/600
1N1126(A)	SI-Di	=1N1124(A):400V	32a$	-	BYX38/600,BYX39/600
1N1127(A)	Si-Di	=1N1124(A):500V	32a$	-	BYX38/600,BYX39/600
1N1128(A)	Si-Di	=1N1124(A):600V	32a$	-	BYX38/600,BYX39/600
1N113	Ge-Di	Gl,S,70V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1130	Si-Di	Gl-L,1500V,0,3A	32a$	USA	-
1N1131	SI-Di	=1N1130:	32b&	-	-
1N1132(R)	Si-Di	UHF,S/X-Band-M,7,5GHz	Koax	USA	-
1N1133	Si-Di	kV-Gl,1,5kV,0,075A	31a	USA	1N5181
1N1134	Si-Di	kV-Gl,1,5kV,0,1A	31a	USA	1N5181
1N1135	Si-Di	kV-Gl,1,8kV,0,065A	31a	USA	1N5181
1N1136	Si-Di	kV-Gl,1,8kV,0,085A	31a	USA	1N5181
1N1137	Si-Di	kV-Gl,2,4kV,0,05A	31a	USA	1N5181
1N1138	Si-Di	kV-Gl,2,4kV,0,06A	31a	USA	1N5181
1N1139	SI-Di	kV-Gl,3,6kV,0,065A	31a	USA	1N5181
1N114	Ge-Di	Gl,S,70V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1140	Si-Di	kV-Gl,3,6kV,0,065A	31a	USA	1N5181
1N1141	Si-Di	kV-Gl,4,8kV,0,06A	31a	USA	1N5182
1N1142	SI-Di	kV-Gl,4,8kV,0,05A	31a	USA	1N5182
1N1143	Si-Di	kV-Gl,6kV,0,05A	31a	USA	1N5183
1N1143A	Si-Di	=1N1143:0,065mA	31a	USA	1N5183
1N1144	SI-Di	kV-Gl,7,2kV,0,05A	31a	USA	1N5183
1N1145	Si-Di	kV-Gl,7,2kV,0,06A	31a	USA	1N5183

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1N1146	Si-Di	kV-Gl,8kV,0,045A	31a	USA	1N5184
1N1147	Si-Di	kV-Gl,12kV,0,045A	31a	USA	1N3052
1N1148	Si-Di	kV-Gl,14kV,0,05A	31a	USA	1N3053
1N1149	Si-Di	kV-Gl,16kV,0,045A	31a	USA	1N3054
1N115	Ge-Di	Gl,S,70V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1150(A)	Si-Di	kV-Gl,1,6kV,0,75A,A:Dual	-	USA	-
1N1157	Si-Di	Gl-L,50V,20A(Tc=100o)	-	Edi	BYX25/600,SSiE2040
1N1158	Si-Di	=1N1157:100V	-		BYX25/600,SSiE2040
1N1159	Si-Di	=1N1157:200V	-		BYX25/600,SSiE2040
1N116(A)	Ge-Di	Uni,60V,30mA,1pF(0V),A:70V	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N1160	Si-Di	=1N1157:300V	-		BYX25/600,SSiE2040
1N1161	Si-Di	Gl-L,50V,35A(Tc=100o)	-	Edi	BYX96/300
1N1162	Si-Di	=1N1161:100V	-		BYX96/300
1N1163	Si-Di	=1N1161:200V	-		BYX96/300
1N1164	Si-Di	=1N1161:300V	-		BYX96/300
1N1165	Si-Di	Gl-L,50V,100A(Tc=100o)	-	Edi	DS75-02B
1N1166	Si-Di	=1N1165:100V	-		DS75-02B
1N1167	Si-Di	=1N1165:200V	-		DS75-02B
1N1168	Si-Di	=1N1165:300V	-		DS75-04B
1N1169	Si-Di	Gl,400V,0,79A	31a	Inr,Sem	BY126..127,BY133..134,1N4004..07,+
1N1169A	Si-Di	=1N1169:	34a	-	BY126..127,BY133..134,1N4004..07,+
1N117(A)	Ge-Di	Uni,60V,30mA,1pF(0V),A:70V	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N1170	Ge-Di	Uni,50V	31a	-	AA117..118,AA132..134,1N34,1N54,+
1N1171	Si-Di	=1N1157	-	Edi	→1N1157
1N1172	Si-Di	=1N1158	-	Edi	→1N1158
1N1173	Si-Di	=1N1159	-	Edi	→1N1159
1N1174	Si-Di	=1N1160	-	Edi	→1N1160
1N1175	Si-Di	=1N1161	-	Edi	→1N1161
1N1176	Si-Di	=1N1162	-	Edi	→1N1162
1N1177	Si-Di	=1N1163	-	Edi	→1N1163
1N1178	Si-Di	=1N1164	-	Edi	→1N1164
1N1179	Si-Di	=1N1165	-	Edi	→1N1165
1N118(A)	Ge-Di	Uni,60V,30mA,0,5pF(0V),A:70mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N1180	Si-Di	=1N1166	-	Edi	→1N1166
1N1181	Si-Di	=1N1167	-	Edi	→1N1167
1N1182	Si-Di	=1N1168	-	Edi	→1N1168
1N1183	Si-Di	Gl-L,50V,35A(Tc=140o)	32a$	USA,EUR	1N3765,1N4525
1N1183A..1190A..	Si-Di	=1N1183..1190:40A(Tc=150o)	-		-
1N1183R...1190R.	Si-Di	=1N1183..1190:	32b&	-	1N3765R
1N1183R..1190R..	Si-Di	-	32b&	-	1N3765R
1N1183T...1190T..	Si-Di	=1N1183..1190:	73a$	-	1N3765T
1N1183T..1190T...	Si-Di	-	73a$	-	1N3765T
1N1183TR..1190TR	Si-Di	=1N1183..1190:	73b&	-	1N3765TR
1N1184	Si-Di	=1N1183:100V	32a$	-	TN3765,1N4525
1N1185	Si-Di	=1N1183:150V	32a$	-	1N3765,1N4525
1N1186	Si-Di	=1N1183:200V	32a$	-	1N3765,1N4525
1N1187	Si-Di	=1N1183:300V	32a$	-	1N3765,1N4526
1N1188	Si-Di	=1N1183:400V	32a$	-	1N3765,1N4526
1N1189	Si-Di	=1N1183:500V	32a$	-	1N3765,1N4527
1N119	Ge-Di	Uni,S,60V,25mA,<500ns	31a	USA	AAY28,1N191..192,1N276
1N1190	Si-Di	=1N1183:600V	32a$	-	1N3765,1N4527
1N1191(A)	Si-Di	Gl-L,50V,20A(Tc=150o)	32a$	USA,EUR	1N3765,1N4525
1N1191R...1198R.	Si-Di	=1N1191..1198:	32b&	-	1N3765R
1N1191R..1198R..	Si-Di	-	32b&	-	1N3765R
1N1192(A)	Si-Di	=1N1191:100V	32a$	-	1N3765,1N4525
1N1193(A)	Si-Di	=1N1191:150V	32a$	-	1N3765,1N4525
1N1194(A)	Si-Di	=1N1191:200V	32a$	-	1N3765,1N4525
1N1195(A)	Si-Di	=1N1191:300V	32a$	-	1N3765,1N4526
1N1196(A)	Si-Di	=1N1191:400V	32a$	-	1N3765,1N4526
1N1197(A)	Si-Di	=1N1191:500V	32a$	-	1N3765,1N4527
1N1198(A)	Si-Di	=1N1191:600V	32a$	-	1N3765,1N4527
1N1199(A,B,C)	Si-Di	Gl-L,50V,12A(150o)	32a$	Gen,Inr,Mot,Rca,Tix,++	BYW88/50,BYX75
1N120	Ge-Di	Uni,S,60V,25mA,<500ns	31a	USA	AAY28,1N191..192,1N276
1N1200(A,B,C)	Si-Di	=1N1199:100V	32a$	-	BYW88/100,BYX76

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1N1201(A,B,C)	Si-Di	=1N1199:150V	32a$	-	BYW88/200,BYX77
1N1201R...1206R	Si-Di	=1N1199..1206:	32b&	-	BYW88/..R,BYX75R..79R
1N1201R..1206R	Si-Di	-	32b&	-	BYW88/..R,BYX75R..79R
1N1202(A,B,C)	Si-Di	=1N1199:200V	32a$	-	BYW88/200,BYX77
1N1203(A,B,C)	Si-Di	=1N1199:300V	32a$	-	BYW88/300,BYX78
1N1204(A,B,C)	Si-Di	=1N1199:400V	32a$	-	BYW88/400,BYX78
1N1205(A,B,C)	Si-Di	=1N1199:500V	32a$	-	BYW88/500,BYX79
1N1206(A,B,C)	Si-Di	=1N1199:600V	32a$	-	BYW88/600,BYX79
1N1217(A,B)	Si-Di	Gl,50V,1,6A	34a	USA	BY251..255,BYW52..56,1N5060..62,+
1N1218(A,B)	Si-Di	=1N1217:100V	34a	-	BY251..255,BYW52..56,1N5060..62,+
1N1219(A,B)	Si-Di	=1N1217:150V	34a	-	BY251..255,BYW52..56,1N5060..62,+
1N1220(A,B)	Si-Di	=1N1217:200V	34a	-	BY251..255,BYW52..56,1N5060..62,+
1N1221(A,B)	Si-Di	=1N1217:300V	34a	-	BY252..255,BYW53..56,1N5060..62,+
1N1222(A,B)	Si-Di	=1N1217:400V	34a	-	BY252..255,BYW53..56,1N5060..62,+
1N1223(A,B)	Si-Di	=1N1217:500V	34a	-	BY253..255,BYW54..56,1N5061..62,+
1N1224(A,B)	Si-Di	=1N1217:600V	34a	-	BY253..255,BYW54..56,1N5061..62,+
1N1225(A,B)	Si-Di	=1N1217:700V	34a	-	BY254..255,BYW55..56,1N5062,+
1N1226(A,B)	Si-Di	=1N1217:800V	34a	-	BY254..255,BYW55..56,1N5062,+
1N1227(A,B)	Si-Di	=1N1217:	32a$	-	BYX38/300,BYX39/600
1N1228(A,B)	Si-Di	=1N1218:	32a$	-	BYX38/300,BYX39/600
1N1229(A,B)	Si-Di	=1N1219:	32a$	-	BYX38/300,BYX39/600
1N1230(A,B)	Si-Di	=1N1220:	32a$	-	BYX38/300,BYX39/600
1N1231(A,B)	Si-Di	=1N1221:	32a$	-	BYX38/300,BYX39/600
1N1232(A,B)	Si-Di	=1N1222:	32a$	-	BYX38/300,BYX39/600
1N1233(A,B)	Si-Di	=1N1223:	32a$	-	BYX38/600,BYX39/600
1N1234(A,B)	Si-Di	=1N1224:	32a$	-	BYX38/600,BYX39/600
1N1235(A,B)	Si-Di	=1N1225:	32a$	-	BYX38/900,BYX39/800
1N1236(A,B)	Si-Di	=1N1226:	32a$	-	BYX38/900,BYX39/800
1N1237	Si-Di	Dual,Gl,1600V,0,75A	-	USA	-
1N1238	Si-Di	Dual,Gl,1600V,0,75A	-	USA	-
1N1239	Si-Di	Dual,Gl,2800V,0,5A	-	USA	-
1N124(A)	Ge-Di	UHF-M,25mA	Koax	Tun	-
1N1240...1250	Si-Di	~1N1251..1261	-	USA	→1N1251..1261
1N1240..1250	Si-Di	-		USA	-
1N125	Ge-Di	HF/S,30V,30mA	-	Tun	-
1N1251	Si-Di	Gl,50V,0,5A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N1252	Si-Di	=1N1251:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N1253	Si-Di	=1N1251:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1254	Si-Di	=1N1251:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1255(A)	Si-Di	=1N1251:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1256	Si-Di	=1N1251:500V,0,32A	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1257	Si-Di	=1N1251:600V,0,3A	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1258	Si-Di	=1N1251:700V,0,28A	34a	-	BY127,BY133,BYX95,1N4006..07,+
1N1259	Si-Di	=1N1251:800V,0,27A	34a	-	BY127,BY133,BYX95,1N4006..07,+
1N126(A)	Ge-Di	Uni,60V,30mA,1pF(0V),A:75V	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N1260	Si-Di	=1N1251:900V,0,25A	34a	-	BY127,BY133,BYX95,1N4007,+
1N1261	Si-Di	=1N1251:1000V,0,24A	34a	-	BY127,BY133,BYX95,1N4007,+
1N1262	Si-Di	kv-Gl,4,5kV,0,25A	-	USA	-
1N1263	Si-Di	Gl,50V,150A	-		-
1N1263A...1266A	Si-Di	=1N1263..1266:200A	-		-
1N1263A..1266A	Si-Di	-		-	-
1N1264	Si-Di	=1N1263:100V	-		-
1N1265	Si-Di	=1N1263:200V	-		-
1N1266	Si-Di	=1N1263:300V	-		-
1N1267	Si-Di	Gl-L,50V,150A	-		-
1N1267A...1270A	Si-Di	=1N1267..1270:200A	-		-
1N1267A..1270A	Si-Di	-		-	-
1N1268	Si-Di	=1N1267:100V	-		-
1N1269	Si-Di	=1N1267:200V	-		-
1N127(A)	Ge-Di	Uni,100V,30mA,1pF(0V),A:125V	31a	USA,Tho	AA117..118,AA132..133
1N1270	Si-Di	=1N1267:300V	-		-
1N1271...1277	Si-Di	~1N1281..1287	-		-
1N1271..1277	Si-Di	-		-	-
1N128(A)	Ge-Di	Uni,40V,30mA,1pF(0V)	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+

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1N1281	Si-Di	Gl-L,50V,160A	73a$	USA	-
1N1282	Si-Di	=1N1281:100V	73a$	-	-
1N1283	Si-Di	=1N1281:150V	73a$	-	-
1N1284	Si-Di	=1N1281:200V	73a$	-	-
1N1285	Si-Di	=1N1281:300V	73a$	-	-
1N1286	Si-Di	=1N1281:400V	73a$	-	-
1N1287	Si-Di	=1N1281:500V	73a$	-	-
1N1291...1297	Si-Di	~1N1281..1287	73a$	-	-
1N1291..1297	Si-Di	-	73a$	-	-
1N1301	Si-Di	Gl-L,50V,37A(Tc=120o)	32a$	USA	1N3765,1N4525
1N1302	Si-Di	=1N1301:100V	32a$	-	1N3765,1N4525
1N1304	Si-Di	=1N1301:200V	32a$	-	1N3765,1N4525
1N1306	Si-Di	=1N1301:300V	32a$	-	1N3765,1N4526
1N1313	Z-Di	8,75V,10%,0,15W	2c	USA	BZX55/..,BZX79/..,ZPD..,1N5238..74,+
1N1313A...1327A	Z-Di	=1N1313..1327:5%	2c	-	-
1N1313A..1327A	Z-Di	=1N1313..1327:8,75V..127,5V,0,15W,5%	2c	-	-
1N1314	Z-Di	=1N1313:10,5V	2c	-	-
1N1315	Z-Di	=1N1313:12,75V	2c	-	-
1N1316	Z-Di	=1N1313:15,75V	2c	-	-
1N1317	Z-Di	=1N1313:19V	2c	-	-
1N1318	Z-Di	=1N1313:23,5V	2c	-	-
1N1319	Z-Di	=1N1313:28,5V	2c	-	-
1N132	Ge-Di	UHF-M,25V,50mA	31a	Kem	-
1N1320	Z-Di	=1N1313:34,5V	2c	-	-
1N1321	Z-Di	=1N1313:41V	2c	-	-
1N1322	Z-Di	=1N1313:48,5V	2c	-	-
1N1323	Z-Di	=1N1313:58V	2c	-	-
1N1324	Z-Di	=1N1313:71V	2c	-	-
1N1325	Z-Di	=1N1313:87,5V	2c	-	-
1N1326	Z-Di	=1N1313:105V	2c	-	-
1N1327	Z-Di	=1N1313:127,5V	2c	-	-
1N1329	Si-Di	Gl,1500V,0,1A	-	Tix	BAY91,BY203/16,BY584,RGP01/16,+
1N133	Ge-Di	HF-Dem,5V	31a	USA	-
1N1330	Si-Di	Gl-L,50V,240A(Tc=125o)	?73a$	Sem,Ssi	-
1N1331	Si-Di	=1N1330:100V	?73a$	-	-
1N1332	Si-Di	=1N1330:150V	?73a$	-	-
1N1333	Si-Di	=1N1330:200V	?73a$	-	-
1N1334	Si-Di	=1N1330:300V	?73a$	-	-
1N1335	Si-Di	=1N1330:400V	?73a$	-	-
1N1336	Si-Di	=1N1330:500V	?73a$	-	-
1N134	Si-Di	UHF-Dem,5V,fmax=400MHz	-	Kem	-
1N1341(A,B,C)	Si-Di	Gl-L,50V,6A(Tc=150o)	32a$	Gen,Mot,Tho++	BYX38/300,BYX39/600
1N1341R...1348R	Si-Di	=1N1341..1348:	32b&	-	BYX38/600R,BYX39/600R
1N1341R..1348R	Si-Di	-	32b&	-	BYX38/600R,BYX39/600R
1N1342(A,B,C)	Si-Di	=1N1341:100V	32a$	-	BYX38/300,BYX39/600
1N1343(A,B,C)	Si-Di	=1N1341:150V	32a$	-	BYX38/300,BYX39/600
1N1344(A,B,C)	Si-Di	=1N1341:200V	32a$	-	BYX38/300,BYX39/600
1N1345(A,B,C)	Si-Di	=1N1341:300V	32a$	-	BYX38/300,BYX39/600
1N1346(A,B,C)	Si-Di	=1N1341:400V	32a$	-	BYX38/600,BYX39/600
1N1347(A,B,C)	Si-Di	=1N1341:500V	32a$	-	BYX38/600,BYX39/600
1N1348(A,B,C)	Si-Di	=1N1341:600V	32a$	-	BYX38/600,BYX39/600
1N135	Ge-Di	Uni,75V	31a	USA,Tho	AA117..118,AA132..133,1N34,1N54
1N1351	Z-Di	10V,10%,10W(Tc=55o)	32b&	USA,Sie	BZX98/..,BZY93/..,1N2974..3005
1N1351A...1375A	Z-Di	=1N1351..1375:5%	32b&	-	-
1N1351A..1375A	Z-Di	=1N1351..1375:5%	32b&	-	-
1N1351B...1375B	Z-Di	=1N1351..1375:20%	32b&	-	-
1N1351B..1375B	Z-Di	=1N1351..1375:20%	32b&	-	-
1N1351C...1375C	Z-Di	=1N1351..1375:bidirektional	32b&	-	-
1N1351C..1375C	Z-Di	=1N1351..1375:Bidirectional	32b&	-	-
1N1351CA..1375CA	Z-Di	=1N1351..1375:bidirektional,5%	32b&	-	-
1N1351R...1375R	Z-Di	=1N1351..1375:	32a$	-	-
1N1351R..1375R	Z-Di	=1N1351..1375:Reverse	32a$	-	-
1N1352	Z-Di	=1N1351:11V	32b&	-	-
1N1353	Z-Di	=1N1351:12V	32b&	-	-

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1N1354	Z-Di	=1N1351:13V	32b&	-	-
1N1355	Z-Di	=1N1351:15V	32b&	-	-
1N1356	Z-Di	=1N1351:16V	32b&	-	-
1N1357	Z-Di	=1N1351:18V	32b&	-	-
1N1358	Z-Di	=1N1351:20V	32b&	-	-
1N1359	Z-Di	=1N1351:22V	32b&	-	-
1N136	Si-Di	UHF-M, fmax=1,3GHz	-	Syl	-
1N1360	Z-Di	=1N1351:24V	32b&	-	-
1N1361	Z-Di	=1N1351:27V	32b&	-	-
1N1362	Z-Di	=1N1351:30V	32b&	-	-
1N1363	Z-Di	=1N1351:33V	32b&	-	-
1N1364	Z-Di	=1N1351:36V	32b&	-	-
1N1365	Z-Di	=1N1351:39V	32b&	-	-
1N1366	Z-Di	=1N1351:43V	32b&	-	-
1N1367	Z-Di	=1N1351:47V	32b&	-	-
1N1368	Z-Di	=1N1351:51V	32b&	-	-
1N1369	Z-Di	=1N1351:56V	32b&	-	-
1N137	Si-N+R	=RT1N137L(Typ-Code/Stempel/marking)	7(9mm)	Mit	→RT1N137L
1N137(A,B)	Si-Di	Uni, 32V, A:36V, 30mA, B:36V, 75mA	2c	USA	BA127, BA147/50, 1N4148, 1N5194..96,+
1N1370	Z-Di	=1N1351:62V	32b&	-	-
1N1371	Z-Di	=1N1351:68V	32b&	-	-
1N1372	Z-Di	=1N1351:75V	32b&	-	-
1N1373	Z-Di	=1N1351:82V	32b&	-	-
1N1374	Z-Di	=1N1351:91V	32b&	-	-
1N1375	Z-Di	=1N1351:100V	32b&	-	-
1N1376	Si-Di	GI-L, 50V, 240A(Tc=125oC)	?73a$	Sem, Ssi	-
1N1377	Si-Di	=1N1376:100V	?73a$	-	-
1N1378	Si-Di	=1N1376:150V	?73a$	-	-
1N1379	Si-Di	=1N1376:200V	?73a$	-	-
1N138(A,B)	Si-Di	Uni, 16V, A:18V, 50mA, B:18V, 9mA	2c	USA	BA127, BA147/25, 1N4148, 1N5194..96,+
1N1380	Si-Di	=1N1376:300V	?73a$	-	-
1N1381	Si-Di	=1N1376:400V	?73a$	-	-
1N1382	Si-Di	=1N1376:500V	?73a$	-	-
1N139	Ge-Di	Uni, 46V, 70mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54,+
1N1396	Si-Di	GI-L, 50V, 70A(Tc=150o)	73a$	Sem, Ssi	1N3288
1N1397	Si-Di	=1N1396:100V	73a$	-	1N3288
1N1398	Si-Di	=1N1396:150V	73a$	-	1N3289
1N1399	Si-Di	=1N1396:200V	73a$	-	1N3289
1N140	Ge-Di	Uni, 80V, 85mA	31a	USA	AA117..118, AA132..133, 1N34, 1N54
1N1400	Si-Di	=1N1396:300V	73a$	-	1N3290
1N1401	Si-Di	=1N1396:400V	73a$	-	1N3291
1N1402	Si-Di	=1N1396:500V	73a$	-	1N3292
1N1403	Si-Di	=1N1396:600V	73a$	-	1N3293
1N1406	Si-Di	GI, 600V, 0,125A	34a	Inr, Sem, Ssi	BY203/12, RGP01/10, SHG1
1N1407	Si-Di	=1N1406:800V	34a	-	BY203/12, RGP01/10, SHG1
1N1408	Si-Di	=1N1406:1000V	34a	-	BY203/12, RGP01/10, SHG1
1N1409	Si-Di	=1N1406:1200V	34a	-	BY203/12, RGP01/12, SHG1,5
1N141	Ge-Di	Uni, HF-Dem, 80V, 70mA	31a	USA	AA113, 1N34, 1N54
1N1410	Si-Di	=1N1406:1500V	31a	-	BY203/16, RGP01/16, SHG1,5
1N1411	Si-Di	=1N1406:1800V	31a	-	BY203/20, SHG2
1N1412	Si-Di	=1N1406:2000V	31a	-	BY203/20, SHG2
1N1413	Si-Di	=1N1406:2400V	31a	-	SHG2,5
1N1414	Si-Di	GI, 400V, 10A	-	Whs	BYX42/600, BYX98/600, SSiD0440
1N1415	Si-Di	GI, 400V, 1A	?34a	USA	BY126..127, BY133..134, 1N4004..07,+
1N1416	Z-Di	8,2V, 5%, 10W	32	Sem, Ssi	BZX98/.., BZY93/.., 1N2972..3011
1N1417	Z-Di	=1N1416:12V	32	-	-
1N1418	Z-Di	=1N1416:15V	32	-	-
1N1419	Z-Di	=1N1416:18V	32	-	-
1N142	Ge-Di	Uni, 115V, 60mA	31a	USA	AA117..118, AA132..133
1N1420	Z-Di	=1N1416:22V	32	-	-
1N1421	Z-Di	=1N1416:27V	32	-	-
1N1422	Z-Di	=1N1416:68V	32	-	-
1N1423	Z-Di	=1N1416:100V	32	-	-
1N1424	Z-Di	=1N1416:150V	32	-	-

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1N1425	Z-Di	8,2V,5%,1W	?34a	Sem,Ssi	BZW22/..,BZX61/..,ZPY..,1N5923..53,+
1N1426	Z-Di	=1N1425:12V	?34a	-	-
1N1427	Z-Di	=1N1425:15V	?34a	-	-
1N1428	Z-Di	=1N1425:18V	?34a	-	-
1N1429	Z-Di	=1N1425:22V	?34a	-	-
1N143	Ge-Di	Uni,115V,85mA	31a	USA	AA117..118,AA132..133
1N1430	Z-Di	=1N1425:27V	?34a	-	-
1N1431	Z-Di	=1N1425:68V	?34a	-	-
1N1432	Z-Di	=1N1425:100V	?34a	-	-
1N1433	Z-Di	=1N1425:150V	?34a	-	-
1N1434	Si-Di	Gl-L,50V,30A	32a$	USA	1N3765,1N4525
1N1435	SI-Di	=1N1434:100V	32a$	-	1N3765,1N4525
1N1436	Si-Di	=1N1434:200V	32a$	-	1N3765,1N4525
1N1437	Si-Di	=1N1434:400V	32a$	-	1N3765,1N4526
1N1438	Si-Di	=1N1434:600V	32a$	-	1N3765,1N4526
1N1439	Si-Di	Gl,100V,0,75A	31a	USA	BY126..127,BY133..135,1N4002..07,+
1N144	Ge-Di	Uni,35V,150mA	31a	USA	AA136,1N270
1N1440	Si-Di	=1N1439:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N1441	Si-Di	=1N1439:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N1442	Si-Di	=1N1439:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N1443(A,B)	Si-Di	Gl,1000V,1,6A,A:0,95A,B:1,6A	34a	USA	BY255,BYW56,GP15M,1N5399,+
1N1444(A,B)	Si-Di	=1N1443(A,B):	?32a	-	-
1N1445	Si-Di	Gl,300V,0,2A	-		BA157..159,BAY21,BAY88..90,+
1N1446	Si-Di	Gl,100V,1,5A(Tc=120o)	-	Scn,Sem	-
1N1447	Si-Di	=1N1446:200V	-		-
1N1448	Si-Di	=1N1446:300V	-		-
1N1449	Si-Di	=1N1446:400V	-		-
1N145	Ge-Di	Uni,40V,0,7A(ss)	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N1450	Si-Di	Gl,100V,1,5A(Tc=100o)	-	Scn,Sem	-
1N1451	Si-Di	=1N1450:200V	-		-
1N1452	Si-Di	=1N1450:300V	-		-
1N1453	Si-Di	=1N1450:400V	-		-
1N1454	Si-Di	Gl-L,100V,25A	-	Ssi	-
1N1455	Si-Di	=1N1454:200V	-		-
1N1456	Si-Di	=1N1454:300V	-		-
1N1457	Si-Di	=1N1454:400V	-		-
1N1458	Si-Di	Gl-L,100V,35A	-	Ssi	-
1N1459	Si-Di	=1N1458:200V	-		-
1N1460	Si-Di	=1N1458:300V	-		-
1N1461	Si-Di	=1N1458:400V	-		-
1N1462	Si-Di	Gl-L,100V,50A	-	Ssi	-
1N1463	Si-Di	=1N1462:200V	-		-
1N1464	Si-Di	=1N1462:300V	-		-
1N1465	Si-Di	=1N1462:400V	-		-
1N1466	Si-Di	Gl-L,100V,75A	-	Ssi	-
1N1467	Si-Di	=1N1466:200V	-		-
1N1468	Si-Di	=1N1466:300V	-		-
1N1469	Si-Di	=1N1466:400V	-		-
1N147(A)	Ge-Di	UHF-M,2V,20mA,910MHz	31a	Phc,Tho	-
1N1470	Si-Di	Gl-L,100V,100A	-	Ssi	-
1N1471	Si-Di	=1N1470:200V	-		-
1N1472	Si-Di	=1N1470:300V	-		-
1N1473	Si-Di	=1N1470:400V	-		-
1N1474	Si-Di	Gl-L,100V,150A	-	Ssi	-
1N1475	Si-Di	=1N1474:200V	-		-
1N1476	Si-Di	=1N1474:300V	-		-
1N1477	Si-Di	=1N1474:400V	-		-
1N1478	Si-Di	Gl-L,100V,200A	-	Ssi	-
1N1479	Si-Di	=1N1478:200V	-		-
1N148	Ge-Di	Dem,15V	-	Cbs	-
1N1480	Si-Di	=1N1478:300V	-		-
1N1481	Si-Di	=1N1478:400V	-		-
1N1482	Z-Di	4,7V,5%,10W	32	USA	BZX98/..,BZY93/..,1N3995..3998
1N1483	Z-Di	6,2V,5%,10W	32	-	-

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1N1484	Z-Di	4,7V,5%,1W	?34a	USA	BZW22/..,BZX61/..,ZPY..,1N5917..20,+
1N1485	Z-Di	6,2V,5%,1W	?34a	-	-
1N1486	Si-Di	Gl,500V,0,78A	34a	USA	BY126..127,BY133..134,1N4005..07,+
1N1487	Si-Di	Gl,100V,0,75A	34a	USA,Tix	BY126..127,BY133..135,1N4002..07,+
1N1488	Si-Di	=1N1487:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1489	Si-Di	=1N1487:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N149	Si-Di	UHF,X-Band-M,9375MHz	Koax	USA	-
1N1490	Si-Di	=1N1487:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1491	Si-Di	=1N1487:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1492	Si-Di	=1N1487:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N150	Si-Di	UHF,C-Band-M,6750MHz	Koax	USA	-
1N1507	Z-Di	3,9V,10%,0,75W	34a	USA,Mot	BZV85/..,BZW22/..,ZPY..,1N4730..50,+
1N1507A...1517A	Z-Di	=1N1507..1517:5%	34a	-	-
1N1507A..1517A	Z-Di	=1N1507..1517:5%	34a	-	-
1N1508	Z-Di	=1N1507:4,7V	34a	-	-
1N1509	Z-Di	=1N1507:5,6V	34a	-	-
1N151	Ge-Di	Gl,100V,1,2A	(Stack)	Gen	-
1N1510	Z-Di	=1N1507:6,8V	34a	-	-
1N1511	Z-Di	=1N1507:8,2V	34a	-	-
1N1512	Z-Di	=1N1507:10V	34a	-	-
1N1513	Z-Di	=1N1507:12V	34a	-	-
1N1514	Z-Di	=1N1507:15V	34a	-	-
1N1515	Z-Di	=1N1507:18V	34a	-	-
1N1516	Z-Di	=1N1507:22V	34a	-	-
1N1517	Z-Di	=1N1507:27V	34a	-	-
1N1518	Z-Di	3,9V,10%,1W	34a	USA,Mot	BZW22/..,BZX61/..,ZPY..,1N5915..35,+
1N1518A...1528A	Z-Di	=1N1518..1528:5%	34a	-	-
1N1518A..1528A	Z-Di	=1N1518..1528:5%	34a	-	-
1N1519	Z-Di	=1N1518:4,7V	34a	-	-
1N152	Ge-Di	Gl,200V,1A	(Stack)	Gen	-
1N1520	Z-Di	=1N1518:5,6V	34a	-	-
1N1521	Z-Di	=1N1518:6,8V	34a	-	-
1N1522	Z-Di	=1N1518:8,2V	34a	-	-
1N1523	Z-Di	=1N1518:10V	34a	-	-
1N1524	Z-Di	=1N1518:12V	34a	-	-
1N1525	Z-Di	=1N1518:15V	34a	-	-
1N1526	Z-Di	=1N1518:18V	34a	-	-
1N1527	Z-Di	=1N1518:22V	34a	-	-
1N1528	Z-Di	=1N1518:27V	34a	-	-
1N153	Ge-Di	Gl,300V,0,75A	(Stack)	Gen	-
1N1530	Ref-Di	8,4V,n0,002%/oC,5%,0,25W	-	Inr,Mot,++	BZX53,1N3156,1N4777,1N4782
1N1530A	Ref-Di	=1N1530:0,001%/oC	-		BZX54,1N3157,1N4778,1N4783
1N1537	Si-Di	Gl-L,50V,1,6A(Tc=140o)	32a$	USA	BYX38/300,BYX39/600
1N1538	Si-Di	=1N1537:100V	32a$	-	BYX38/300,BYX39/600
1N1539	Si-Di	=1N1537:150V	32a$	-	BYX38/300,BYX39/600
1N1540	Si-Di	=1N1537:200V	32a$	-	BYX38/300,BYX39/600
1N1541	Si-Di	=1N1537:300V	32a$	-	BYX38/300,BYX39/600
1N1542	Si-Di	=1N1537:400V	32a$	-	BYX38/600,BYX39/600
1N1543	Si-Di	=1N1537:500V	32a$	-	BYX38/600,BYX39/600
1N1544	Si-Di	=1N1537:600V	32a$	-	BYX38/600,BYX39/600
1N155S(A)	Si-Di	UHF-Dem,9GHz,A:10GHz	Koax	Syl	-
1N1551	Si-Di	Gl-L,100V,1A(Tc=100o)	32a$	USA	BYX38/300,BYX39/600
1N1552	Si-Di	=1N1551:200V	32a$	-	BYX38/300,BYX39/600
1N1553	Si-Di	=1N1551:300V	32a$	-	BYX38/300,BYX39/600
1N1554	Si-Di	=1N1551:400V	32a$	-	BYX38/600,BYX39/600
1N1555	Si-Di	=1N1551:500V	32a$	-	BYX38/600,BYX39/600
1N1556	Si-Di	Gl,100V,0,75A(Tc=100o)	34a	USA	BY126..127,BY133..135,1N4002..07,+
1N1557	Si-Di	=1N1556:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1558	Si-Di	=1N1556:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1559	Si-Di	=1N1556:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N156	Si-Di	UHF,X-Band-M,9375MHz	Koax	Syl	-
1N1560	Si-Di	=1N1556:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1561	Ge-Di	25V	-	-	-
1N1562	Ge-Di	25V	-	-	-

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1N1563(A)	Si-Di	GI,100V,1,5A	?2c	Sem,Ssi	BY251..255,BYW52..56,1N5392..99,+
1N1564(A)	Si-Di	=1N1563:200V	?2c	-	BY251..255,BYW52..56,1N5393..99,+
1N1565(A)	Si-Di	=1N1563:300V	?2c	-	BY252..255,BYW53..56,1N5394..99,+
1N1566(A)	Si-Di	=1N1563:400V	?2c	-	BY252..255,BYW53..56,1N5395..99,+
1N1567(A)	Si-Di	=1N1563:500V	?2c	-	BY253..255,BYW54..56,1N5396..99,+
1N1568(A)	Si-Di	=1N1563:600V	?2c	-	BY253..255,BYW54..56,1N5398..99,+
1N1569	Si-Di	GI,100V,1A	-	Mot	BY126..127,BY133..135,1N4002..07,+
1N157	Si-Di	?1N21	-		-
1N1570	Si-Di	=1N1569:200V	-		BY126..127,BY133..134,1N4003..07,+
1N1571	Si-Di	=1N1569:300V	-		BY126..127,BY133..134,1N4004..07,+
1N1572	Si-Di	=1N1569:400V	-		BY126..127,BY133..134,1N4004..07,+
1N1573	Si-Di	=1N1569:500V	-		BY126..127,BY133..134,1N4005..07,+
1N1574	Si-Di	=1N1569:600V	-		BY126..127,BY133..134,1N4005..07,+
1N1575	Si-Di	GI-L,100V,3,5A(Tc=25o)	21	Gie,Mot,Ssi	BYX38/300,BYX39/600
1N1576	Si-Di	=1N1575:200V	21	-	BYX38/300,BYX39/600
1N1577	Si-Di	=1N1575:300V	21	-	BYX38/300,BYX39/600
1N1578	Si-Di	=1N1575:400V	21	-	BYX38/600,BYX39/600
1N1579	Si-Di	=1N1575:500V	21	-	BYX38/600,BYX39/600
1N158	Ge-Di	GI,300V,0,5A	(Stack)	Gen	-
1N1580	Si-Di	=1N1575:600V	21	-	BYX38/600,BYX39/600
1N1581	Si-Di	GI-L,50V,10A(Tc=50o)	32a$	USA,Tho	BYW88/50,BYX42/300,BYX98/300,+
1N1581R...1587R	Si-Di	=1N1581..1587:	32b&	-	BYW88/..R,BYX42/..R,BYX98/..R,+
1N1581R..1587R	Si-Di	-	32b&	-	BYW88/..R,BYX42/..R,BYX98/..R..
1N1582	Si-Di	=1N1581:100V	32a$	-	BYW88/100,BYX42/300,BYX98/300,+
1N1583	Si-Di	=1N1581:200V	32a$	-	BYW88/200,BYX42/300,BYX98/300,+
1N1584	Si-Di	=1N1581:300V	32a$	-	BYW88/300,BYX42/300,BYX98/300,+
1N1585	Si-Di	=1N1581:400V	32a$	-	BYW88/400,BYX42/600,BYX98/600,+
1N1586	Si-Di	=1N1581:500V	32a$	-	BYW88/500,BYX42/600,BYX98/600,+
1N1587	Si-Di	=1N1581:600V	32a$	-	BYW88/600,BYX42/600,BYX98/600,+
1N1588	Z-Di	3,9V,10%,3,5W	32a$	USA,Mot	BZX98/..,BZY93/..,1N2970..2988
1N1588A...1598A	Z-Di	=1N1588..1598:5%	32a$	-	-
1N1588A..1598A	Z-Di	=1N1588..1598:5%	32a$	-	-
1N1589	Z-Di	=1N1588:4,7V	32a$	-	-
1N1590	Z-Di	=1N1588:5,6V	32a$	-	-
1N1591	Z-Di	=1N1588:6,8V	32a$	-	-
1N1592	Z-Di	=1N1588:8,2V	32a$	-	-
1N1593	Z-Di	=1N1588:10V	32a$	-	-
1N1594	Z-Di	=1N1588:12V	32a$	-	-
1N1595	Z-Di	=1N1588:15V	32a$	-	-
1N1596	Z-Di	=1N1588:18V	32a$	-	-
1N1597	Z-Di	=1N1588:22V	32a$	-	-
1N1598	Z-Di	=1N1588:27V	32a$	-	-
1N1599	Z-Di	3,9V,10%,10W	32a$	USA,Mot	BZX98/..,BZY93/..,1N2970..2988
1N1599A...1609A	Z-Di	=1N1599..1609:5%	32a$	-	-
1N1599A..1609A	Z-Di	=1N1599..1609:5%	32a$	-	-
1N160	Si-Di	UHF,C-Band-M,6750MHz	Koax	USA	-
1N1600	Z-Di	=1N1599:4,7V	32a$	-	-
1N1601	Z-Di	=1N1599:5,6V	32a$	-	-
1N1602	Z-Di	=1N1599:6,8V	32a$	-	-
1N1603	Z-Di	=1N1599:8,2V	32a$	-	-
1N1604	Z-Di	=1N1599:10V	32a$	-	-
1N1605	Z-Di	=1N1599:12V	32a$	-	-
1N1606	Z-Di	=1N1599:15V	32a$	-	-
1N1607	Z-Di	=1N1599:18V	32a$	-	-
1N1608	Z-Di	=1N1599:22V	32a$	-	-
1N1609	Z-Di	=1N1599:27V	32a$	-	-
1N1610	Si-Di	UHF,S/X-Band-Dem,7,7GHz	Koax	USA	-
1N1611(A,B)	Si-Di	UHF,C/X-Band-Dem,9GHz	Koax	USA	-
1N1612(A)	Si-Di	GI-L,50V,15A(Tc=50o)	32a$	Gen,Idc,Rca,Tix,++	BYX25/600,BYX99/300
1N1612R..1616R	Si-Di	=1N1612..1616:	32b&	-	BYX25/..R,BYX99/..R,SSiE2040
1N1613(A)	Si-Di	=1N1612:100V	32a$	-	BYX25/600,BYX99/300
1N1614(A)	Si-Di	=1N1612:200V	32a$	-	BYX25/600,BYX99/300
1N1615(A)	Si-Di	=1N1612:400V	32a$	-	BYX25/600,BYX99/600
1N1616(A)	Si-Di	=1N1612:600V	32a$	-	BYX25/600,BYX99/600

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1N1617	Si-Di	Gl,100V,1,5A	31a	Sem	BY251..255,BY226..227,1N5392..99,+
1N1618	Si-Di	=1N1617:200V	31a	-	BY251..255,BY226..227,1N5393..99,+
1N1619	SI-Di	=1N1617:300V	31a	-	BY252..255,BY226..227,1N5394..99,+
1N1620	Si-Di	=1N1617:400V	31a	-	BY252..255,BY226..227,1N5395..99,+
1N1621	Si-Di	Gl-L,100V,10A(Tc=100o)	32a	Sem	BYW88/100,BYX76..81,2N4506..11,+
1N1622	Si-Di	=1N1621:200V	32a	-	BYW88/200,BYX77..81,2N4506..11,+
1N1623	Si-Di	=1N1621:300V	32a	-	BYW88/300,BYX78..81,2N4507..11,+
1N1624	Si-Di	=1N1621:400V	32a	-	BYW88/400,BYX78..81,2N4507..11,+
1N1625(A)	Se-Di	Gl,48V,0,25..0,5mA	?36	Edl	-
1N1626(A)	Se-Di	Gl,96V,0,25..0,5mA	?36	Edl	-
1N1627	Se-Di	Gl,48V,3,8mA	?36	Edl	-
1N1628	Se-Di	Gl,96V,3,8mA	?36	Edl	-
1N1629	Se-Di	Gl,144V,3,8mA	?36	Edl	-
1N1630	Se-Di	Gl,192V,3,8mA	?36	Edl	-
1N1631	Se-Di	Gl,240V,3,8mA	?36	Edl	-
1N1632	Se-Di	Gl,288V,3,8mA	?36	Edl	-
1N1633	Se-Di	Gl,336V,3,8mA	?36	Edl	-
1N1634	Se-Di	Gl,384V,3,8mA	?36	Edl	-
1N1635	Se-Di	Gl,48V,13mA	?36	Edl	-
1N1636	Se-Di	Gl,96V,13mA	?36	Edl	-
1N1637	Se-Di	Gl,144V,13mA	?36	Edl	-
1N1638	Se-Di	Gl,192V,13mA	?36	Edl	-
1N1639	Se-Di	Gl,240V,13mA	?36	Edl	-
1N1640	Se-Di	Gl,48V,28mA	?36	Edl	-
1N1641	Se-Di	Gl,96V,28mA	?36	Edl	-
1N1642	Se-Di	Gl,144V,28mA	?36	Edl	-
1N1644	Si-Di	Gl,50V,0,75A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N1645	Si-Di	=1N1644:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N1646	Si-Di	=1N1644:150V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1647	Si-Di	=1N1644:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1648	Si-Di	=1N1644:250V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1649	Si-Di	=1N1644:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1650	Si-Di	=1N1644:350V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1651	Si-Di	=1N1644:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1652	Si-Di	=1N1644:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1653	Si-Di	=1N1644:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1660	Si-Di	Gl-L,50V,116A(Tc=120o)	73a$	USA	1N4587..96
1N1661	Si-Di	=1N1660:100V	73a$	-	1N4587..96
1N1662	Si-Di	=1N1660:150V	73a$	-	1N4588..96
1N1663	Si-Di	=1N1660:200V	73a$	-	1N4588..96
1N1664	Si-Di	=1N1660:300V	73a$	-	1N4589..96
1N1665	Si-Di	=1N1660:400V	73a$	-	1N4590..96
1N1666	Si-Di	=1N1660:500V	73a$	-	1N4591..96
1N1670	Si-Di	Gl-L,50V,240A(Tc=120o)	73a$	Sem,Ssi	1N3735..44
1N1671	Si-Di	=1N1670:100V	73a$	-	1N3735..44
1N1672	Si-Di	=1N1670:150V	73a$	-	1N3736..44
1N1673	Si-Di	=1N1670:200V	73a$	-	1N3736..44
1N1674	Si-Di	=1N1670:300V	73a$	-	1N3737..44
1N1675	Si-Di	=1N1670:400V	73a$	-	1N3738..44
1N1676	Si-Di	=1N1670:500V	73a$	-	1N3739..44
1N1680	Si-Di	Gl-L,150V,50A(Tc=150o)	73a$	Ssi	1N3289..97
1N1681	Si-Di	=1N1680:250V	73a$	-	1N3290..97
1N1682	Si-Di	=1N1680:300V	73a$	-	1N3290..97
1N1683	Si-Di	=1N1680:350V	73a$	-	1N3291..97
1N1684	Si-Di	=1N1680:400V	73a$	-	1N3291..97
1N1685	Si-Di	=1N1680:450V	73a$	-	1N3292..97
1N1686	Si-Di	=1N1680:500V	73a$	-	1N3292..97
1N1687	Si-Di	=1N1680:600V	73a$	-	1N3293..97
1N1688	Si-Di	=1N1680:700V	73a$	-	1N3294..97
1N1689	Si-Di	=1N1680:800V	73a$	-	1N3294..97
1N1690	Si-Di	=1N1680:900V	73a$	-	1N3295..97
1N1691	Si-Di	=1N1680:1000V	73a$	-	1N3295..97
1N1692	Si-Di	Gl,100V,0,75A	34a	USA,Tix	BY126..127,BY133..135,1N4002..07,+
1N1693	Si-Di	=1N1692:200V	34a	-	BY126..127,BY133..134,1N4003..07,+

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1N1694	Si-Di	=1N1692:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1695	Si-Di	=1N1692:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1696	Si-Di	=1N1692:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1697	Si-Di	=1N1692:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1698	Si-Di	kV-Gl,6,6kV,0,062A	31a	Scn,Sem	1N5183..84
1N1699	Si-Di	kV-Gl,10kV,0,058A	31a	Scn,Sem	1N5184
1N1700	Si-Di	kV-Gl,12kV,0,05A	31a	Scn,Sem	1N3052
1N1701	Si-Di	Gl,50V,0,3A	34a	USA	BA157..159,BY206..207,BY401..405,+
1N1702	Si-Di	=1N1701:100V	34a	-	BA157..159,BY206..207,BY402..405,+
1N1703	Si-Di	=1N1701:200V	34a	-	BA157..159,BY206..207,BY403..405,+
1N1704	Si-Di	=1N1701:300V	34a	-	BA157..159,BY206..207,BY404..405,+
1N1705	Si-Di	=1N1701:400V	34a	-	BA157..159,BY207,BY404..405,+
1N1706	Si-Di	=1N1701:500V	34a	-	BA158..159,BY207,BY405,+
1N1707	Si-Di	Gl,50V,0,5A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N1708	Si-Di	=1N1707:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N1709	Si-Di	=1N1707:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N1710	Si-Di	=1N1707:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1711	Si-Di	=1N1707:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N1712	Si-Di	=1N1707:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N172	Di	-		Syl	-
1N173(A)	Di	UHF-M,2V,1GHz	-	USA	-
1N1730	Si-Di	kV-Gl,1kV,0,2A	31a	Gen,Gie,Idc	GP02-20,HVG2,MR250-2
1N1730A	Si-Di	=1N1730:0,35A	31a	Mot,++	-
1N1731	Si-Di	kV-Gl,1,5kV,0,2A	31a	-	GP02-20,HVG2,MR250-2
1N1731A	Si-Di	=1N1731:0,35A	31a	-	-
1N1732	Si-Di	kV-Gl,2kV,0,2A	31a	-	GP02-20,HVG2,MR250-2
1N1732A	Si-Di	=1N1732:0,35A	31a	-	-
1N1733	Si-Di	kV-Gl,3kV,0,2A	31a	-	GP02-30,HVG3,MR250-3
1N1733A	Si-Di	=1N1733:0,35A	31a	-	-
1N1734	Si-Di	kV-Gl,5kV,0,2A	31a	-	HVG5,MR250-5
1N1734A	Si-Di	=1N1734:0,35A	31a	-	-
1N1735(A)	Ref-Di	6,2V,5%,0,2W	31a	USA,Mot	BZV10..11,BZV27..28,1N4580..81,+
1N1736(A)	Ref-Di	12,4V,5%,0,4W	31a	USA,Mot	1N4908..09,1N4912..13
1N1737(A)	Ref-Di	18,6V,5%,0,6W	31a	USA,Mot	-
1N1738(A)	Ref-Di	24,8V,5%,0,8W	31a	USA,Mot	-
1N1739(A)	Ref-Di	31V,5%,1W	31a	USA,Mot	-
1N174	Ge-Di	-		Del	-
1N1740(A)	Ref-Di	37,2V,5%,1,2W	31a	USA,Mot	-
1N1741(A)	Ref-Di	43,4V,5%,1,4W	31a	USA,Mot	-
1N1742(A)	Ref-Di	49,6V,5%,1,6W	31a	USA,Mot	-
1N1743	Z-Di	10V,5%,10W	32a	Wes	BZX98/C10,BZY93/C10,1N2974
1N1744	Z-Di	10V,5%,1W	34a	Sem	BZW22/C10,BZX61/C10,ZPY10,1N5925,+
1N1745	Si-Di	kV-Gl,1,5kV,0,38A	31a	USA	1N1731A
1N1746	Si-Di	kV-Gl,1,5kV,0,44A	31a	USA	-
1N1747	Si-Di	kV-Gl,1,8kV,0,36A	31a	USA	1N1732A
1N1748	Si-Di	kV-Gl,1,8kV,0,42A	31a	USA	-
1N1749	Si-Di	kV-Gl,2,4kV,0,23A	31a	USA	1N1733A
1N175	Ge-Di	Uni,125V	31a	USA	AA133
1N1750	Si-Di	kV-Gl,2,4kV,0,38A	31a	USA	-
1N1751	Si-Di	kV-Gl,3,6kV,0,37A	31a	USA	1N1734A
1N1752	Si-Di	kV-Gl,3,6kV,0,36A	31a	USA	1N1734A
1N1753	Si-Di	kV-Gl,4,8kV,0,33A	31a	USA	1N1734A
1N1754	Si-Di	kV-Gl,4,8kV,0,32A	31a	USA	1N1734A
1N1755	Si-Di	kV-Gl,6kV,0,29A	31a	USA	-
1N1756	Si-Di	kV-Gl,6kV,0,36A	31a	USA	-
1N1757	Si-Di	kV-Gl,7,2kV,0,29A	31a	USA	-
1N1758	Si-Di	kV-Gl,7,2kV,0,33A	31a	USA	-
1N1759	Si-Di	kV-Gl,8kV,0,25A	31a	USA	-
1N1760	Si-Di	kV-Gl,12kV,0,25A	31a	USA	-
1N1761	Si-Di	kV-Gl,14kV,0,3A	31a	USA	-
1N1762	Si-Di	kV-Gl,16kV,0,25A	31a	USA	-
1N1763(A)	Si-Di	Gl,400V,0,5..1A	34a	USA,Rca	BY126..127,BY133..134,1N4004..07,+
1N1764(A)	Si-Di	=1N1763:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N1765	Z-Di	5,6V,10%,1W	34a	USA,Mot	BZW22/..,BZX61/..,ZPY..,1M5919..56,+

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1N1765A...1802A	Z-Di	=1N1765..1802:5%	34a	-	-
1N1765A..1802A..	Z-Di	=1N1765..1802:5%	34a	-	-
1N1766	Z-Di	=1N1765:6,2V	34a	-	-
1N1767	Z-Di	=1N1765:6,8V	34a	-	-
1N1768	Z-Di	=1N1765:7,5V	34a	-	-
1N1769	Z-Di	=1N1765:8,2V	34a	-	-
1N1770	Z-Di	=1N1765:9,1V	34a	-	-
1N1771	Z-Di	=1N1765:10V	34a	-	-
1N1772	Z-Di	=1N1765:11V	34a	-	-
1N1773	Z-Di	=1N1765:12V	34a	-	-
1N1774	Z-Di	=1N1765:13V	34a	-	-
1N1775	Z-Di	=1N1765:15V	34a	-	-
1N1776	Z-Di	=1N1765:16V	34a	-	-
1N1777	Z-Di	=1N1765:18V	34a	-	-
1N1778	Z-Di	=1N1765:20V	34a	-	-
1N1779	Z-Di	=1N1765:22V	34a	-	-
1N1780	Z-Di	=1N1765:24V	34a	-	-
1N1781	Z-Di	=1N1765:27V	34a	-	-
1N1782	Z-Di	=1N1765:30V	34a	-	-
1N1783	Z-Di	=1N1765:33V	34a	-	-
1N1784	Z-Di	=1N1765:36V	34a	-	-
1N1785	Z-Di	=1N1765:39V	34a	-	-
1N1786	Z-Di	=1N1765:43V	34a	-	-
1N1787	Z-Di	=1N1765:47V	34a	-	-
1N1788	Z-Di	=1N1765:51V	34a	-	-
1N1789	Z-Di	=1N1765:56V	34a	-	-
1N1790	Z-Di	=1N1765:62V	34a	-	-
1N1791	Z-Di	=1N1765:68V	34a	-	-
1N1792	Z-Di	=1N1765:75V	34a	-	-
1N1793	Z-Di	=1N1765:82V	34a	-	-
1N1794	Z-Di	=1N1765:91V	34a	-	-
1N1795	Z-Di	=1N1765:100V	34a	-	-
1N1796	Z-Di	=1N1765:110V	34a	-	-
1N1797	Z-Di	=1N1765:120V	34a	-	-
1N1798	Z-Di	=1N1765:130V	34a	-	-
1N1799	Z-Di	=1N1765:150V	34a	-	-
1N1800	Z-Di	=1N1765:160V	34a	-	-
1N1801	Z-Di	=1N1765:180V	34a	-	-
1N1802	Z-Di	=1N1765:200V	34a	-	-
1N1803	Z-Di	5,6V,10%,10W	32b&	USA,Mot,Sie	BZX98/..,BZY93/..,1N2970..3015
1N1803A...1815A	Z-Di	=1N1803..1815:5%	32b&	-	-
1N1803A..1815A..	Z-Di	=1N1803..1815:5%	32b&	-	-
1N1803B...1815B	Z-Di	=1N1803..1815:20%	32b&	-	-
1N1803B..1815B..	Z-Di	=1N1803..1815:20%	32b&	-	-
1N1803C...1815C..	Z-Di	=1N1803..1815:bidirektional	32b&	-	-
1N1803C..1815C...	Z-Di	=1N1803..1815:Bidirectional	32b&	-	-
1N1803CA..1815CA..	Z-Di	=1N1803..1815:bidirektional,5%	32b&	-	-
1N1803R...1815R	Z-Di	=1N1803..1815:	32a$	-	-
1N1803R..1815R..	Z-Di	=1N1803..1815:Reverse	32a$	-	-
1N1804	Z-Di	=1N1803:6,2V	32b&	-	-
1N1805	Z-Di	=1N1803:6,8V	32b&	-	-
1N1806	Z-Di	=1N1803:7,5V	32b&	-	-
1N1807	Z-Di	=1N1803:8,2V	32b&	-	-
1N1808	Z-Di	=1N1803:9,1V	32b&	-	-
1N1809	Z-Di	=1N1803:110V	32b&	-	-
1N1810	Z-Di	=1N1803:120V	32b&	-	-
1N1811	Z-Di	=1N1803:130V	32b&	-	-
1N1812	Z-Di	=1N1803:150V	32b&	-	-
1N1813	Z-Di	=1N1803:160V	32b&	-	-
1N1814	Z-Di	=1N1803:180V	32b&	-	-
1N1815	Z-Di	=1N1803:200V	32b&	-	-
1N1816	Z-Di	13V,10%,10W	32b&	USA,Mot,Sie	BZX98/..,BZY93/..,1N2977..3004
1N1816A...1836A	Z-Di	=1N1816..1836:5%	32b&	-	-
1N1816A..1836A..	Z-Di	=1N1816..1836:5%	32b&	-	-

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1N1816C...1836C..	Z-Di	=1N1816..1836:bidirektional	32b&	-	-
1N1816C..1836C...	Z-Di	=1N1816..1836:Bidirectional	32b&	-	-
1N1816CA..1836CA	Z-Di	=1N1816..1836:bidirektional,5%	32b&	-	-
1N1816R...1836R .	Z-Di	=1N1816..1836:	32a$	-	-
1N1816R..1836R ..	Z-Di	=1N1816..1836:Reverse	32a$	-	-
1N1817	Z-Di	=1N1816:15V	32b&	-	-
1N1818	Z-Di	=1N1816:16V	32b&	-	-
1N1819	Z-Di	=1N1816:18V	32b&	-	-
1N1820	Z-Di	=1N1816:20V	32b&	-	-
1N1821	Z-Di	=1N1816:22V	32b&	-	-
1N1822	Z-Di	=1N1816:24V	32b&	-	-
1N1823	Z-Di	=1N1816:27V	32b&	-	-
1N1824	Z-Di	=1N1816:30V	32b&	-	-
1N1825	Z-Di	=1N1816:33V	32b&	-	-
1N1826	Z-Di	=1N1816:36V	32b&	-	-
1N1827	Z-Di	=1N1816:39V	32b&	-	-
1N1828	Z-Di	=1N1816:43V	32b&	-	-
1N1829	Z-Di	=1N1816:47V	32b&	-	-
1N1830	Z-Di	=1N1816:51V	32b&	-	-
1N1831	Z-Di	=1N1816:56V	32b&	-	-
1N1832	Z-Di	=1N1816:62V	32b&	-	-
1N1833	Z-Di	=1N1816:68V	32b&	-	-
1N1834	Z-Di	=1N1816:75V	32b&	-	-
1N1835	Z-Di	=1N1816:82V	32b&	-	-
1N1836	Z-Di	=1N1816:91V	32b&	-	-
1N1838	Ge-Di	UHF,X/Ku-Band-M,13,5GHz	Koax	USA	-
1N1839	Si-Di	Gl,6,8V,85mA	2c	USA	-
1N1840	Si-Di	Gl,10V,77mA	2c	USA	-
1N1841	Si-Di	Gl,15V,63mA	2c	USA	-
1N1842	Si-Di	Gl,22V,50mA	2c	USA	-
1N1843	Si-Di	Gl,33V,40mA	2c	USA	-
1N1844	Si-Di	Gl,47V,30mA	2c	USA	-
1N1845	Si-Di	Gl,68V,23mA	2c	USA	-
1N1846	Si-Di	Gl,100V,16mA	2c	USA	-
1N1847	Si-Di	Gl,150V,11mA	2c	USA	-
1N1848	Si-Di	Gl,330V,7,5mA	2c	USA	-
1N1850	Si-Di	Gl,470V,6mA	2c	USA	-
1N1851	Si-Di	~1N1839	-		-
1N1852	Si-Di	~1N1840	-		-
1N1853	Si-Di	?1N1841	-		-
1N1854	Si-Di	?1N1842	-		-
1N1855	SI-Di	?1N1843	-		-
1N1856	Si-Di	?1N1844	-		-
1N1857	Si-Di	?1N1845	-		-
1N1858	Si-Di	?1N1846	-		-
1N1859	Si-Di	?1N1847	-		-
1N1860	Si-Di	?1N1848	-		-
1N1861	Si-Di	?1N1849	-		-
1N1862	Si-Di	?1N1850	-		-
1N1863	Si-Di	~1N1839	-		-
1N1864	Si-Di	~1N1840	-		-
1N1865	Si-Di	~1N1841	-		-
1N1866	Si-Di	?1N1842	-		-
1N1867	Si-Di	?1N1843	-		-
1N1868	Si-Di	?1N1844	-		-
1N1869	Si-Di	?1N1845	-		-
1N1870	Si-Di	?1N1846	-		-
1N1871	Si-Di	?1N1847	-		-
1N1872	Si-Di	?1N1848	-		-
1N1873	Si-Di	?1N1849	-		-
1N1874	Si-Di	?1N1850	-		-
1N1875	Z-Di	8,2V,10%,1W	34a	USA	BZW22/..,BZX61/..,ZPY..,1N5923..49,+
1N1875A...1888A .	Z-Di	=1N1875..1888:5%	34a	-	-

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1N1875A..1888A	Z-Di	=1N1875..1888:1W,5%	34a	-	-
1N1875B...1888B	Z-Di	=1N1875..1888:1%	34a	-	-
1N1875B..1888B	Z-Di	=1N1875..1888:1W,1%	34a	-	-
1N1876	Z-Di	=1N1875:10V	34a	-	-
1N1877	Z-Di	=1N1875:12V	34a	-	-
1N1878	Z-Di	=1N1875:15V	34a	-	-
1N1879	Z-Di	=1N1875:18V	34a	-	-
1N188	Opto	-		-	-
1N1880	Z-Di	=1N1875:22V	34a	-	-
1N1881	Z-Di	=1N1875:27V	34a	-	-
1N1882	Z-Di	=1N1875:33V	34a	-	-
1N1883	Z-Di	=1N1875:39V	34a	-	-
1N1884	Z-Di	=1N1875:47V	34a	-	-
1N1885	Z-Di	=1N1875:56V	34a	-	-
1N1886	Z-Di	=1N1875:68V	34a	-	-
1N1887	Z-Di	=1N1875:82V	34a	-	-
1N1888	Z-Di	=1N1875:100V	34a	-	-
1N1889	Z-Di	120V,10%,3W	32a	USA	BZX98/..,BZY93/..,1N3008..3011
1N1889A...1890A	Z-Di	=1N1889..1890:5%	32a	-	-
1N1889A..1890A	Z-Di	=1N1889..1890:120V,3W,5%	32a	-	-
1N1889B...1890B	Z-Di	=1N1889..1890:1%	32a	-	-
1N1889B..1890B	Z-Di	120V,3W,1%	32a	-	-
1N189	Opto	-		-	-
1N1890	Z-Di	=1N1889:145V	32a	-	-
1N1891	Z-Di	8,2V,10%,10W	32	Idc,Ssi	BZX98/..,BZY93/..,1N2972..3011
1N1891A...1906A	Z-Di	=1N1891..1906:5%	32	-	-
1N1891A..1906A	Z-Di	=1N1891..1906:5%	32	-	-
1N1892	Z-Di	=1N1891:10V	32	-	-
1N1893	Z-Di	=1N1891:12V	32	-	-
1N1894	Z-Di	=1N1891:15V	32	-	-
1N1895	Z-Di	=1N1891:18V	32	-	-
1N1896	Z-Di	=1N1891:22V	32	-	-
1N1897	Z-Di	=1N1891:27V	32	-	-
1N1898	Z-Di	=1N1891:33V	32	-	-
1N1899	Z-Di	=1N1891:39V	32	-	-
1N190	Ge-Di	3V		-	-
1N1900	Z-Di	=1N1891:47V	32	-	-
1N1901	Z-Di	=1N1891:56V	32	-	-
1N1902	Z-Di	=1N1891:68V	32	-	-
1N1903	Z-Di	=1N1891:82V	32	-	-
1N1904	Z-Di	=1N1891:100V	32	-	-
1N1905	Z-Di	=1N1891:120V	32	-	-
1N1906	Z-Di	=1N1891:150V	32	-	-
1N1907	Si-Di	GI,50V,1,5A	34a	USA	BY251..255,BY226..227,1N5391..99,+
1N1908	Si-Di	=1N1907:100V	34a	-	BY251..255,BY226..227,1N5392..99,+
1N1909	Si-Di	=1N1907:200V	34a	-	BY251..255,BY226..227,1N5393..99,+
1N191	Ge-Di	S,90V,30mA,<0,5pF,<100ns	31a	USA,Tho	AAY28
1N1910	Si-Di	=1N1907:300V	34a	-	BY252..255,BY226..227,1N5394..99,+
1N1911	Si-Di	=1N1907:400V	34a	-	BY252..255,BY226..227,1N5395..99,+
1N1912	Si-Di	=1N1907:500V	34a	-	BY253..255,BY226..227,1N5396..99,+
1N1913	Si-Di	=1N1907:600V	34a	-	BY253..255,BY226..227,1N5397..99,+
1N1914	Si-Di	=1N1907:700V	34a	-	BY254..255,BY227,1N5398..99,+
1N1915	Si-Di	=1N1907:800V	34a	-	BY254..255,BY227,1N5399,+
1N1916	Si-Di	=1N1907:900V	34a	-	BY255,BY227,BYW56,GP15M,+
1N1917	Si-Di	GI-L,50V,4A	32	Idc,Ssi	BYX38/300,BYX39/600
1N1918	Si-Di	=1N1917:100V	32	-	BYX38/300,BYX39/600
1N1919	Si-Di	=1N1917:200V	32	-	BYX38/300,BYX39/600
1N192	Ge-Di	=1N191:70V	31a	USA,Tho	AAY28
1N1920	Si-Di	=1N1917:300V	32	-	BYX38/300,BYX39/600
1N1921	Si-Di	=1N1917:400V	32	-	BYX38/600,BYX39/600
1N1922	Si-Di	=1N1917:500V	32	-	BYX38/600,BYX39/600
1N1923	Si-Di	=1N1917:600V	32	-	BYX38/600,BYX39/600
1N1924	Si-Di	=1N1917:700V	32	-	BYX38/900,BYX39/800
1N1925	Si-Di	=1N1917:800V	32	-	BYX38/900,BYX39/800

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1N1926	Si-Di	=1N1917:900V	32	-	BYX38/900,BYX39/1000
1N1927	Z-Di	3,9V,10%,0,2W	34a	USA	BZX55/..,BZX79/..,ZPD..,1N5228..71,+
1N1927A...1944A	Z-Di	=1N1927..1944:5%	34a	-	-
1N1927A..1944A..	Z-Di	=1N1927..1944:5%	34a	-	-
1N1927B...1944B	Z-Di	=1N1927..1944:1%	34a	-	-
1N1927B..1944B..	Z-Di	=1N1927..1944:1%	34a	-	-
1N1928	Z-Di	=1N1927:4,7V	34a	-	-
1N1929	Z-Di	=1N1927:5,6V	34a	-	-
1N193	Si-Di	40V,<500ns	-	Syl	-
1N1930	Z-Di	=1N1927:6,8V	34a	-	-
1N1931	Z-Di	=1N1927:8,2V	34a	-	-
1N1932	Z-Di	=1N1927:10V	34a	-	-
1N1933	Z-Di	=1N1927:12V	34a	-	-
1N1934	Z-Di	=1N1927:15V	34a	-	-
1N1935	Z-Di	=1N1927:18V	34a	-	-
1N1936	Z-Di	=1N1927:22V	34a	-	-
1N1937	Z-Di	=1N1927:27V	34a	-	-
1N1938	Z-Di	=1N1927:33V	34a	-	-
1N1939	Z-Di	=1N1927:39V	34a	-	-
1N194(A)	Si-Di	S,40V,30mA,200ns	31a	USA	BAV18..21,BAX15..17,1N4148,+
1N1940	Z-Di	=1N1927:47V	34a	-	-
1N1941	Z-Di	=1N1927:56V	34a	-	-
1N1942	Z-Di	=1N1927:68V	34a	-	-
1N1943	Z-Di	=1N1927:82V	34a	-	-
1N1944	Z-Di	=1N1927:100V	34a	-	-
1N1945	Z-Di	120V,10%,0,2W	31a	USA	BZX55/..,BZX79/..,ZPD..,1N5273..81,..
1N1945A..1953A..	Z-Di	=1N1945..1953:5%	31a	-	-
1N1945B..1953B..	Z-Di	=1N1945..1953:1%	31a	-	-
1N1946	Z-Di	=1N1945:145V	31a	-	-
1N1947	Z-Di	=1N1945:180V	31a	-	-
1N1948	Z-Di	=1N1945:220V	31a	-	-
1N1949	Z-Di	=1N1945:270V	31a	-	-
1N195	Si-Di	S,40V,30mA,300ns	31a	USA	BAV18..21,BAX15..17,1N4148,+
1N1950	Z-Di	=1N1945:330V	31a	-	-
1N1951	Z-Di	=1N1945:395V	31a	-	-
1N1952	Z-Di	=1N1945:470V	31a	-	-
1N1953	Z-Di	=1N1945:565V	31a	-	-
1N1954	Z-Di	3,95V,10%,0,4W	31a	USA	BZX55/..,BZX83/..,ZPD..,1N5228..57,+
1N1954A..1965A..	Z-Di	=1N1954..1965:5%	31a	-	-
1N1954B..1965B..	Z-Di	=1N1954..1965:1%	31a	-	-
1N1955	Z-Di	=1N1954:4,7V	31a	-	-
1N1956	Z-Di	=1N1954:5,65V	31a	-	-
1N1957	Z-Di	=1N1954:6,85V	31a	-	-
1N1958	Z-Di	=1N1954:8,3V	31a	-	-
1N1959	Z-Di	=1N1954:9,7V	31a	-	-
1N196	Si-Di	S,40V,30mA,100ns	31a	USA	BAV18..21,BAX15..17,1N4148,+
1N1960	Z-Di	=1N1954:12V	31a	-	-
1N1961	Z-Di	=1N1954:14,5V	31a	-	-
1N1962	Z-Di	=1N1954:18V	31a	-	-
1N1963	Z-Di	=1N1954:22V	31a	-	-
1N1964	Z-Di	=1N1954:27V	31a	-	-
1N1965	Z-Di	=1N1954:33V	31a	-	-
1N1966	Z-Di	39,5V,10%,0,4W	34a	Sem	BZX55/..,BZX83/..,ZPD..,1N5259..81,+
1N1967	Z-Di	=1N1966:47V	34a	-	-
1N1968	Z-Di	=1N1966:56,5V	34a	-	-
1N1969	Z-Di	=1N1966:68,5V	34a	-	-
1N197	Si-Di	~2x1N21	-		-
1N1970	Z-Di	=1N1966:83V	34a	-	-
1N1971	Z-Di	=1N1966:100V	34a	-	-
1N1972	Z-Di	=1N1966:120V	34a	-	-
1N1973	Z-Di	=1N1966:150V	34a	-	-
1N1974	Z-Di	=1N1966:180V	34a	-	-
1N1975	Z-Di	=1N1966:220V	34a	-	-
1N1976	Z-Di	=1N1966:270V	34a	-	-

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1N1977	Z-Di	=1N1966:330V	34a	-	-
1N1978	Z-Di	=1N1966:390V	34a	-	-
1N1979	Z-Di	=1N1966:470V	34a	-	-
1N198(A..N)	Ge-Di	Uni,S,100V,30mA,<300ns	31a	USA,Tho	AAY28,1N191
1N1980	Z-Di	=1N1966:560V	34a	-	-
1N1981	Z-Di	3,9V,10%,0,15W	2c	USA	BZX55/..,BZX79/..,ZPD..,1N5228..81,+
1N1981A...2007A	Z-Di	=1N1981..2007:5%	2c	-	-
1N1981A..2007A	Z-Di	=1N1981..2007:5%	2c	-	-
1N1981B...2007B	Z-Di	=1N1981..2007:1%	2c	-	-
1N1981B..2007B	Z-Di	=1N1981..2007:1%	2c	-	-
1N1982	Z-Di	=1N1981:4,7V	2c	-	-
1N1983	Z-Di	=1N1981:5,6V	2c	-	-
1N1984	Z-Di	=1N1981:6,8V	2c	-	-
1N1985	Z-Di	=1N1981:8,2V	2c	-	-
1N1986	Z-Di	=1N1981:10V	2c	-	-
1N1987	Z-Di	=1N1981:12V	2c	-	-
1N1988	Z-Di	=1N1981:15V	2c	-	-
1N1989	Z-Di	=1N1981:18V	2c	-	-
1N1990	Z-Di	=1N1981:22V	2c	-	-
1N1991	Z-Di	=1N1981:27V	2c	-	-
1N1992	Z-Di	=1N1981:33V	2c	-	-
1N1993	Z-Di	=1N1981:39V	2c	-	-
1N1994	Z-Di	=1N1981:47V	2c	-	-
1N1995	Z-Di	=1N1981:56V	2c	-	-
1N1996	Z-Di	=1N1981:68V	2c	-	-
1N1997	Z-Di	=1N1981:82V	2c	-	-
1N1998	Z-Di	=1N1981:100V	2c	-	-
1N1999	Z-Di	=1N1981:120V	2c	-	-
1N200	Z-Di	6,8V,10%,0,15W	2c	USA	BZX55/..,BZX79/..,ZPD..,1N5235..81,+
1N2000	Z-Di	=1N1981:150V	2c	-	-
1N2001	Z-Di	=1N1981:180V	2c	-	-
1N2002	Z-Di	=1N1981:220V	2c	-	-
1N2003	Z-Di	=1N1981:270V	2c	-	-
1N2004	Z-Di	=1N1981:330V	2c	-	-
1N2005	Z-Di	=1N1981:390V	2c	-	-
1N2006	Z-Di	=1N1981:470V	2c	-	-
1N2007	Z-Di	=1N1981:560V	2c	-	-
1N2008	Z-Di	100V,10%,10W	32b&	USA,Mot,Sie	BZX98/..,BZY93/..,1N3005..3011
1N2008A...2012A	Z-Di	=1N2008..2012:5%	32b&	-	-
1N2008A..2012A	Z-Di	=1N2008..2012:5%	32b&	-	-
1N2008C...2012C	Z-Di	=1N2008..2012:bidirektional	32b&	-	-
1N2008C..2012C	Z-Di	=1N2008..2012:Bidirectional	32b&	-	-
1N2008CA..2012CA	Z-Di	=1N2008..2012:bidirektional,5%	32b&	-	-
1N2008R...2012R	Z-Di	=1N2008..2012:	32a$	-	-
1N2008R..2012R	Z-Di	=1N2008..2012:Reverse	32a$	-	-
1N2009	Z-Di	=1N2008:110V	32b&	-	-
1N201	Z-Di	=1N200:8,2V	2c	-	-
1N2010	Z-Di	=1N2008:120V	32b&	-	-
1N2011	Z-Di	=1N2008:130V	32b&	-	-
1N2012	Z-Di	=1N2008:150V	32b&	-	-
1N2013	Si-Di	Gl,50V,0,2A	34a	USA	BA157..159,BY206..207,BY204/4,+
1N2014	Si-Di	=1N2013:100V	34a	-	BA157..159,BY206..207,BY204/4,+
1N2015	Si-Di	=1N2013:150V	34a	-	BA157..159,BY206..207,BY204/4,+
1N2016	Si-Di	=1N2013:200V	34a	-	BA157..159,BY206..207,BY204/4,+
1N2017	Si-Di	=1N2013:250V	34a	-	BA157..159,BY206..207,BY204/4,+
1N2018	Si-Di	=1N2013:300V	34a	-	BA157..159,BY206..207,BY204/4,+
1N2019	Si-Di	=1N2013:350V	34a	-	BA157..159,BY206..207,BY204/4,+
1N202	Z-Di	=1N200:10V	2c	-	-
1N2020	Si-Di	=1N2013:400V	34a	-	BA157..159,BY207,BY204/4,+
1N2021	Si-Di	Gl-L,150V,10A(Tc=150o)	32a$	USA	BYW88/200,BYX42/300,BYX77..81,+
1N2022	Si-Di	=1N2021:250V	32a$	-	BYW88/300,BYX42/300,BYX78..81,+
1N2023	Si-Di	=1N2021:300V	32a$	-	BYW88/300,BYX42/300,BYX78..81,+
1N2024	Si-Di	=1N2021:350V	32a$	-	BYW88/400,BYX42/600,BYX78..81,+
1N2025	Si-Di	=1N2021:400V	32a$	-	BYW88/400,BYX42/600,BYX78..81,+

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1N2026	Si-Di	Gl-L,50V,1A(Tc=150o)	32a$	USA	BYX38/300,BYX39/600
1N2027	Si-Di	=1N2026:200V	32a$	-	BYX38/300,BYX39/600
1N2028	Si-Di	=1N2026:300V	32a$	-	BYX38/300,BYX39/600
1N2029	Si-Di	=1N2026:400V	32a$	-	BYX38/600,BYX39/600
1N203	Z-Di	=1N200:12V	2c	-	-
1N2030	Si-Di	=1N2026:500V	32a$	-	BYX38/600,BYX39/600
1N2031	Si-Di	=1N2026:600V	32a$	-	BYX38/600,BYX39/600
1N2032	Z-Di	4,85V,10%,0,75W	34a	USA,Mot	BZV85/..,BZW22/..,ZPY..,1N3016..29,+
1N2032A...2040A	Z-Di	=1N2032..2040:5%	34a	-	-
1N2032A..2040A	Z-Di	=1N2032..2040:5%	34a	-	-
1N2033	Z-Di	=1N2032:5,8V	34a	-	-
1N2034	Z-Di	=1N2032:7,1V	34a	-	-
1N2035	Z-Di	=1N2032:8,75V	34a	-	-
1N2036	Z-Di	=1N2032:10,5V	34a	-	-
1N2037	Z-Di	=1N2032:12,7V	34a	-	-
1N2038	Z-Di	=1N2032:15,7V	34a	-	-
1N2039	Z-Di	=1N2032:19V	34a	-	-
1N204	Z-Di	=1N200:15V	2c	-	-
1N2040	Z-Di	=1N2032:23,5V	34a	-	-
1N2041	Z-Di	4,85V,10%,10W	32	USA,Mot,Sie	BZX98/..,BZY93/..,1N2970..86
1N2041...49A..D	Z-Di	=1N2041..2049:?5%	32	-	-
1N2041..2049-1..-4	Z-Di	=1N2041..2049:±5%	32	-	-
1N2041..2049A..D	Z-Di	=1N2041..2049:±5%	32	-	-
1N2041..49-1..-4..	Z-Di	=1N2041..2049:?5%	32	-	-
1N2042	Z-Di	=1N2041:5,8V	32	-	-
1N2043	Z-Di	=1N2041:7,1V	32	-	-
1N2044	Z-Di	=1N2041:8,75V	32	-	-
1N2045	Z-Di	=1N2041:10,5V	32	-	-
1N2046	Z-Di	=1N2041:12,7V	32	-	-
1N2047	Z-Di	=1N2041:15,7V	32	-	-
1N2048	Z-Di	=1N2041:19V	32	-	-
1N2049	Z-Di	=1N2041:23,5V	32	-	-
1N205	Z-Di	=1N200:18V	2c	-	-
1N2054	Si-Di	Gl-L,50V,250A(Tc=135o)	73a$	USA	1N3735..44
1N2055	Si-Di	=1N2054:100V	73a$	-	1N3735..44
1N2056	Si-Di	=1N2054:150V	73a$	-	1N3736..44
1N2057	Si-Di	=1N2054:200V	73a$	-	1N3736..44
1N2058	Si-Di	=1N2054:250V	73a$	-	1N3737..44
1N2059	Si-Di	=1N2054:300V	73a$	-	1N3737..44
1N206	Z-Di	=1N200:22V	2c	-	-
1N2060	Si-Di	=1N2054:350V	73a$	-	1N3738..44
1N2061	Si-Di	=1N2054:400V	73a$	-	1N3738..44
1N2062	Si-Di	=1N2054:450V	73a$	-	1N3739..44
1N2063	Si-Di	=1N2054:500V	73a$	-	1N3739..44
1N2064	Si-Di	=1N2054:600V	73a$	-	1N3740..44
1N2065	Si-Di	=1N2054:700V	73a$	-	1N3741..44
1N2066	Si-Di	=1N2054:800V	73a$	-	1N3741..44
1N2067	Si-Di	=1N2054:900V	73a$	-	1N3742..44
1N2068	Si-Di	=1N2054:1000V	73a$	-	1N3742..44
1N2069(A)	Si-Di	Gl,Uni,200V,0,75A	31a	Gie,Tix,++	BY126..127,BY133..134,1N4003..07,+
1N207	Z-Di	=1N200:27V	2c	-	-
1N2070(A)	Si-Di	=1N2069:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N2071(A)	Si-Di	=1N2069:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N2072	Si-Di	Gl,50V,0,75A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N2073	Si-Di	=1N2072:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N2074	Si-Di	=1N2072:150V	34a	-	BY126..127,BY133..135,1N4003..07,+
1N2075	Si-Di	=1N2072:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N2076	Si-Di	=1N2072:250V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2077	Si-Di	=1N2072:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2078	Si-Di	=1N2072:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2079	Si-Di	=1N2072:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N208	Z-Di	=1N200:33V	2c	-	-
1N2080	Si-Di	Gl,50V,0,5A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N2081	Si-Di	=1N2080:100V	34a	-	BY126..127,BY133..135,1N4002..07,+

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1N2082	Si-Di	=1N2080:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N2083	Si-Di	=1N2080:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2084	Si-Di	=1N2080:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2085	Si-Di	=1N2080:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2086	Si-Di	=1N2080:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2088	Si-Di	Gl,500V,0,75A	-		BY126..127,BY133..134,1N4005..07,+
1N2089	Si-Di	=1N2088:600V	-		BY126..127,BY133..134,1N4005..07,+
1N209	Z-Di	=1N200:39V	2c	-	-
1N2090	Si-Di	Gl,50V,0,75A	?36a	USA	BY126..127,BY133..135,1N4001..07,+
1N2091	Si-Di	=1N2090:100V	?36a	-	BY126..127,BY133..135,1N4002..07,+
1N2092	Si-Di	=1N2090:200V	?36a	-	BY126..127,BY133..134,1N4003..07,+
1N2093	Si-Di	=1N2090:300V	?36a	-	BY126..127,BY133..134,1N4004..07,+
1N2094	Si-Di	=1N2090:400V	?36a	-	BY126..127,BY133..134,1N4004..07,+
1N2095	Si-Di	=1N2090:500V	?36a	-	BY126..127,BY133..134,1N4005..07,+
1N2096	Si-Di	=1N2090:600V	?36a	-	BY126..127,BY133..134,1N4005..07,+
1N21	Si-Di	UHF,S-Band-M,2,5V,30mA,3060MHz	Koax	Nec,Tho,++	-
1N210	Z-Di	=1N200:47V	2c	-	-
1N2102	Si-Di	UHF,L/S-Band-Dem,3295MHz	Koax	USA	-
1N2103	Si-Di	Gl,50V,0,75A	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N2104	Si-Di	=1N2103:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N2105	Si-Di	=1N2103:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N2106	Si-Di	=1N2103:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2107	Si-Di	=1N2103:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2108	Si-Di	=1N2103:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2109	Si-Di	Gl-L,50V,2A	32	Idc,Sem	(BY249/300,BYX38/300,BYX39/600,++)
1N211	Z-Di	=1N200:56V	2c	-	-
1N2110	Si-Di	=1N2109:100V	32	-	(BY249/300,BYX38/300,BYX39/600,++)
1N2111	Si-Di	=1N2109:200V	32	-	(BY249/300,BYX38/300,BYX39/600,++)
1N2112	Si-Di	=1N2109:300V	32	-	(BY249/300,BYX38/300,BYX39/600,++)
1N2113	Si-Di	=1N2109:400V	32	-	(BY249/600,BYX38/600,BYX39/600,++)
1N2114	Si-Di	=1N2109:500V	32	-	(BY249/600,BYX38/600,BYX39/600,++)
1N2115	Si-Di	Gl,365V,0,3A	?36a	USA	BA157..159,BY206..207,BY204/4,+
1N2116	Si-Di	Gl,400V,0,75A	34a	USA	BY126..127,BY133..134,1N4004..07,+
1N2117	Si-Di	Gl,720V,0,75A	34a	USA	BY127,BY133,BYW42,1N4006..07,+
1N212	Z-Di	=1N200:68V	2c	-	-
1N2127(A)	Si-Di	UHF,L/X-Band-Dem,9375MHz	Koax	USA	-
1N2128	Si-Di	Gl-L,50V,60A(Tc=115o)	32a$	USA	-
1N2128A...2138A	Si-Di	=1N2128..2138:60A(Tc=140o)	32a$	-	-
1N2128A..2138A	Si-Di	-	32a$	-	-
1N2128R...2138R	Si-Di	=1N2128..2138:	32b&	-	DS75-02B..-16B
1N2128R..2138R	Si-Di	-	32b&	-	DS75-02B..-16B
1N2129	Si-Di	=1N2128:100V	32a$	-	-
1N213	Z-Di	=1N200:82V	2c	-	-
1N2130	Si-Di	=1N2128:150V	32a$	-	-
1N2131	Si-Di	=1N2128:200V	32a$	-	-
1N2132	Si-Di	=1N2128:250V	32a$	-	-
1N2133	Si-Di	=1N2128:300V	32a$	-	-
1N2134	Si-Di	=1N2128:350V	32a$	-	-
1N2135	Si-Di	=1N2128:400V	32a$	-	-
1N2136	Si-Di	=1N2128:450V	32a$	-	-
1N2137	Si-Di	=1N2128:500V	32a$	-	-
1N2138	Si-Di	=1N2128:600V	32a$	-	-
1N2139	Si-Di	kV-Gl,20kV,0,045A	31a	USA	1N3057
1N214	Z-Di	=1N200:100V	2c	-	-
1N2146	Si-Di	Gl,5,120V,<50ns	34a	Wes	BAV15..16,EGP10C,FE1C
1N2147(A)	Si-Di	Gl-L,50V,6A(Tc=150o)	32a	USA	BYX38/300,BYX39/600
1N2148(A)	Si-Di	=1N2147:100V	32a	-	BYX38/300,BYX39/600
1N2149(A)	Si-Di	=1N2147:200V	32a	-	BYX38/300,BYX39/600
1N215	Z-Di	=1N200:120V	2c	-	-
1N2150(A)	Si-Di	=1N2147:300V	32a	-	BYX38/300,BYX39/600
1N2151(A)	Si-Di	=1N2147:400V	32a	-	BYX38/600,BYX39/600
1N2152(A)	Si-Di	=1N2147:500V	32a	-	BYX38/600,BYX39/600
1N2153(A)	Si-Di	=1N2147:600V	32a	-	BYX38/600,BYX39/600
1N2154	Si-Di	Gl-L,50V,25A(Tc=145o)	32a$	USA	1N3765..68,1N4525..30

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1N2154R...2160R	Si-Di	=1N2154..2160:	32b&	-	1N3765R..68R
1N2154R..2160R	Si-Di	-	32b&	-	1N3765R..68R
1N2155	Si-Di	=1N2154:100V	32a$	-	1N3765..68,1N4525..30
1N2156	Si-Di	=1N2154:200V	32a$	-	1N3765..68,1N4525..30
1N2157	Si-Di	=1N2154:300V	32a$	-	1N3765..68,1N4526..30
1N2158	Si-Di	=1N2154:400V	32a$	-	1N3765..68,1N4526..30
1N2159	Si-Di	=1N2154:500V	32a$	-	1N3765..68,1N4527..30
1N216	Z-Di	=1N200:150V	2c	-	-
1N2160	Si-Di	=1N2154:600V	32a$	-	1N3765..68,1N4527..30
1N2163(A)	Ref-Di	9,4V,0,75W	34a	USA,Mot,Sie	-
1N2164(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2165(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2166(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2167(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2168(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2169(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N217	Z-Di	=1N200:180V	2c	-	-
1N2170(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2171(A)	Ref-Di	9,4V,0,75W	34a	-	-
1N2172	Si-Di	Gl-L,50V,50A(Tc=150o)	73a$	USA	1N3288..97
1N2173	Si-Di	=1N2172:100V	73a$	-	1N3288..97
1N2174	Si-Di	=1N2172:200V	73a$	-	1N3289..97
1N2175	Opto	-		-	-
1N2176	Si-Di	Gl,50V,3A	-		BY251..255,BYW82,GP30A,1N5400..08,+
1N2177	Si-Di	=1N2176:100V	-		BY251..255,BYW82,GP30B,1N5401..08,+
1N2178	Si-Di	=1N2176:150V	-		BY251..255,BYW82,GP30D,1N5402..08,+
1N2179	Si-Di	=1N2176:200V	-		BY251..255,BYW82,GP30D,1N5402..08,+
1N218	Z-Di	=1N200:220V	2c	-	-
1N2180	Si-Di	=1N2176:300V	-		BY252..255,BYW83,GP30G,1N5403..08,+
1N2181	Si-Di	=1N2176:400V	-		BY252..255,BYW83,GP30G,1N5404..08,+
1N2182	Si-Di	=1N2176:500V	-		BY253..255,BYW84,GP30J,1N5405..08,+
1N2183	Si-Di	=1N2176:600V	-		BY253..255,BYW84,GP30J,1N5406..08,+
1N2184	Si-Di	Gl,50V,3A	-		BY251..255,BYW82,GP30A,1N5400..08,+
1N2185	Si-Di	=1N2184:100V	-		BY251..255,BYW82,GP30B,1N5401..08,+
1N2186	Si-Di	=1N2184:150V	-		BY251..255,BYW82,GP30D,1N5402..08,+
1N2187	Si-Di	=1N2184:200V	-		BY251..255,BYW82,GP30D,1N5402..08,+
1N2188	Si-Di	=1N2184:300V	-		BY252..255,BYW83,GP30G,1N5403..08,+
1N2189	Si-Di	=1N2184:400V	-		BY252..255,BYW83,GP30G,1N5404..08,+
1N219	Z-Di	=1N200:270V	2c	-	-
1N2190	Si-Di	=1N2184:500V	-		BY253..255,BYW84,GP30J,1N5405..08,+
1N2191	Si-Di	=1N2184:600V	-		BY253..255,BYW84,GP30J,1N5406..08,+
1N2192	Si-Di	=1N2184:800V	-		BY254..255,BYW85,GP30K,1N5407..08,+
1N2193	Si-Di	=1N2184:1000V	-		BY255,BYW86,GP30M,1N5408,+
1N2194	Si-Di	Gl-L,50V,6A	32	-	BYX38/300,BYX39/600
1N2195	Si-Di	=1N2194:100V	32	-	BYX38/300,BYX39/600
1N2196	Si-Di	=1N2194:150V	32	-	BYX38/300,BYX39/600
1N2197	Si-Di	=1N2194:200V	32	-	BYX38/300,BYX39/600
1N2198	Si-Di	=1N2194:300V	32	-	BYX38/300,BYX39/600
1N2199	Si-Di	=1N2194:400V	32	-	BYX38/600,BYX39/600
1N22	Si-Di	UHF,X-Band-Dem,4V,30mA,9375MHz	Koax	Nec	-
1N220	Z-Di	=1N200:330V	2c	-	-
1N2200	Si-Di	=1N2194:500V	32	-	BYX38/600,BYX39/600
1N2201	Si-Di	=1N2194:600V	32	-	BYX38/600,BYX39/600
1N2202	Si-Di	=1N2194:800V	32	-	BYX38/900,BYX39/800
1N2203	Si-Di	=1N2194:1000V	32	-	BYX38/1200,BYX39/1000
1N2204	Si-Di	Gl-L,50V,12A	32	-	BYW88/50,BYX75..81,BYX99/300,+
1N2205	Si-Di	=1N2204:100V	32	-	BYW88/100,BYX76..81,BYX99/300,+
1N2206	Si-Di	=1N2204:150V	32	-	BYW88/200,BYX77..81,BYX99/300,+
1N2207	Si-Di	=1N2204:200V	32	-	BYW88/200,BYX77..81,BYX99/300,+
1N2208	Si-Di	=1N2204:300V	32	-	BYW88/300,BYX78..81,BYX99/300,+
1N2209	Si-Di	=1N2204:400V	32	-	BYW88/400,BYX78..81,BYX99/600,+
1N221	Z-Di	=1N200:390V	2c	-	-
1N2210	Si-Di	=1N2204:500V	32	-	BYW88/500,BYX79..81,BYX99/600,+
1N2211	Si-Di	=1N2204:600V	32	-	BYW88/600,BYX79..81,BYX99/600,+

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1N2212	Si-Di	=1N2204:800V	32	-	BYW88/800,BYX80..81,BYX99/900,+
1N2213	Si-Di	=1N2204:1000V	32	-	BYW88/1000,BYX81,BYX99/1200,+
1N2214	Z-Di	5,5V,2%,1W	34a	USA	BZW22/C5V6,BZX61/C5V6,ZPY5,6,1N5919+
1N2216(A)	Si-Di	GI-L,50V,1,5A	32a$	USA	BYX38/300,BYX39/600
1N2217(A)	Si-Di	=1N2216:Iso	32a	-	-
1N2218(A)	Si-Di	=1N2216:500V	32a$	-	BYX38/600,BYX39/600
1N2219(A)	Si-Di	=1N2216:500V,Iso	32a	-	-
1N222	Z-Di	=1N200:470V	2c	-	-
1N2220(A)	Si-Di	=1N2216:600V	32a$	-	BYX38/600,BYX39/600
1N2221(A)	Si-Di	=1N2216:600V,Iso	32a	-	-
1N2222(A)	Si-Di	GI-L,800V,1A	32a$	USA	BYX38/900,BYX39/800
1N2223(A)	Si-Di	=1N2222:Iso	32a	-	-
1N2224(A)	Si-Di	=1N2222:1000V	32a$	-	BYX38/1200,BYX39/1000
1N2225(A)	Si-Di	=1N2222:1000V,Iso	32a	-	-
1N2226(A)	Si-Di	=1N2222:1200V	32a$	-	BYX38/1200,BYX39/1200
1N2227(A)	Si-Di	=1N2222:1200V,Iso	32a	-	-
1N2228(A)	Si-Di	GI-L,50V,5A	32a$	USA	BYX38/300,BYX39/600
1N2229(A)	Si-Di	=1N2228:Iso	32a	-	-
1N2230(A)	Si-Di	=1N2228:200V	32a$	-	BYX38/300,BYX39/600
1N2231(A)	Si-Di	=1N2228:200V,Iso	32a	-	-
1N2232(A)	Si-Di	=1N2228:300V	32a$	-	BYX38/300/,BYX39/600
1N2233(A)	SI-Di	=1N2228:300V,Iso	32a	-	-
1N2234(A)	Si-Di	=1N2228:400V	32a$	-	BYX38/600,BYX39/600
1N2235(A)	Si-Di	=1N2228:400V,Iso	32a	-	-
1N2236(A)	SI-Di	=1N2228:500V	32a$	-	BYX38/600,BYX39/600
1N2237(A)	Si-Di	=1N2228:500V,Iso	32a	-	-
1N2238(A)	Si-Di	=1N2228:600V	32a$	-	BYX38/600,BYX39/600
1N2239(A)	Si-Di	=1N2228:600V,Iso	32a	-	-
1N2240(A)	SI-Di	=1N2228:800V	32a$	-	BYX38/900,BYX39/800
1N2241(A)	Si-Di	=1N2228:800V,Iso	32a	-	-
1N2242(A)	Si-Di	=1N2228:1000V	32a$	-	BYX38/1200,BYX39/1000
1N2243(A)	Si-Di	=1N2228:1000V,Iso	32a	-	-
1N2244(A)	SI-Di	=1N2228:1200V	32a$	-	BYX38/1200,BYX39/1200
1N2245(A)	SI-Di	=1N2228:1200V,Iso	32a	-	-
1N2246(A)	Si-Di	GI-L,50V,10A	32a$	USA	BYX42/300,BYX98/300
1N2247(A)	Si-Di	=1N2246:Iso	32a	-	-
1N2248(A)	Si-Di	=1N2246:100V	32a$	-	BYX42/300,BYX98/300
1N2249(A)	SI-Di	=1N2246:100V,Iso	32a	-	-
1N225	Z-Di	8,75V,10%,0,15W	2c	USA	BZX55/..,BZX79/..,ZPD..,1N5238..74,+
1N2250(A)	Si-Di	=1N2246:200V	32a$	-	BYX42/300,BYX98/300
1N2251(A)	Si-Di	=1N2246:200V,Iso	32a	-	-
1N2252(A)	Si-Di	=1N2246:300V	32a$	-	BYX42/300,BYX98/300
1N2253(A)	Si-Di	=1N2246:300V,Iso	32a	-	-
1N2254(A)	Si-Di	=1N2246:400V	32a$	-	BYX42/600,BYX98/600
1N2255(A)	Si-Di	=1N2246:400V,Iso	32a	-	-
1N2256(A)	Si-Di	=1N2246:500V	32a$	-	BYX42/600,BYX98/600
1N2257(A)	Si-Di	=1N2246:500V,Iso	32a	-	-
1N2258(A)	Si-Di	=1N2246:600V	32a$	-	BYX42/600,BYX98/600
1N2259(A)	Si-Di	=1N2246:600V,Iso	32a	-	-
1N225A...235A	Z-Di	=1N225..235:5%	2c	-	-
1N225A..235A	Z-Di	=1N225..235:5%	2c	-	-
1N226	Z-Di	=1N225:10,5V	2c	-	-
1N2260(A)	Si-Di	=1N2246:800V	32a$	-	BYX42/900,BYX98/900
1N2261(A)	Si-Di	=1N2246:800V,Iso	32a	-	-
1N2262(A)	Si-Di	=1N2246:1000V	32a$	-	BYX42/1200,BYX98/1200
1N2263(A)	Si-Di	=1N2246:1000V,Iso	32a	-	-
1N2264(A)	Si-Di	=1N2246:1200V	32a$	-	BYX42/1200,BYX98/1200
1N2265(A)	Si-Di	=1N2246:1200V,Iso	32a	-	-
1N2266	Si-Di	GI-L,50V,1A	32a$	USA	BYX38/300,BYX39/600
1N2267	Si-Di	=1N2266:Iso	32a	-	-
1N2268	Si-Di	=1N2266:500V	32a$	-	BYX38/600,BYX39/600
1N2269	Si-Di	=1N2266:500V,Iso	32a	-	-
1N227	Z-Di	=1N225:12,8V	2c	-	-
1N2270	Si-Di	=1N2266:600V	32a$	-	BYX38/600,BYX39/600

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1N2271	Si-Di	=1N2266:600V,Iso	32a	-	-
1N2272	Si-Di	Gl-L,50V,6A(Tc=150o)	32a$	USA	BYX38/300,BYX39/600
1N2273	Si-Di	=1N2272:100V	32a$	-	BYX38/300,BYX39/600
1N2274	Si-Di	=1N2272:200V	32a$	-	BYX38/300,BYX39/600
1N2275	Si-Di	=1N2272:300V	32a$	-	BYX38/300,BYX39/600
1N2276	Si-Di	=1N2272:400V	32a$	-	BYX38/600,BYX39/600
1N2277	Si-Di	=1N2272:500V	32a$	-	BYX38/600,BYX39/600
1N2278	Si-Di	=1N2272:600V	32a$	-	BYX38/600,BYX39/600
1N2279	Si-Di	=1N2272:800V	32a$	-	BYX38/900,BYX39/800
1N228	Z-Di	=1N225:15,7V	2c	-	-
1N2280	Si-Di	=1N2272:1000V	32a$	-	BYX38/1200,BYX39/1000
1N2281	Si-Di	=1N2272:1200V	32a$	-	BYX38/1200,BYX39/1200
1N2282	Si-Di	Gl-L,300V,20A(Tc=150o)	32a$	USA	1N3765..68,1N4525..30
1N2283	Si-Di	=1N2282:400V	32a$	-	1N3765..68,1N4526..30
1N2284	Si-Di	=1N2282:500V	32a$	-	1N3765..68,1N4527..30
1N2285	Si-Di	=1N2282:600V	32a$	-	1N3765..68,1N4527..30
1N2286	Si-Di	=1N2282:800V	32a$	-	1N3766..68,1N4528..30
1N2287	Si-Di	=1N2282:1000V	32a$	-	1N3768,1N4529..30
1N2288	Si-Di	=1N2282:1200V	32a$	-	1N4530
1N2289...2293	Si-Di	=1N2289A..2293A:Iso	32a	-	-
1N2289..2293	Si-Di	-	32a	-	-
1N2289A	Si-Di	Gl-L,100V,1,5A	32a$	USA	BYX38/300,BYX39/600
1N229	Z-Di	=1N225:19V	2c	-	-
1N2290A	Si-Di	=1N2289A:5A	32a$	-	BYX38/300,BYX39/600
1N2291A	Si-Di	=1N2289A:200V	32a$	-	BYX38/300,BYX39/600
1N2292A	Si-Di	=1N2289A:300V	32a$	-	BYX38/300,BYX39/600
1N2293A	Si-Di	=1N2289A:400V	32a$	-	BYX38/600,BYX39/600
1N2294	Si-Di	Gl-L,50V,22A	-		BYX25/600,SSiE2040
1N2295	Si-Di	=1N2294:100V	-		BYX25/600,SSiE2040
1N2296	Si-Di	=1N2294:150V	-		BYX25/600,SSiE2040
1N2297	Si-Di	=1N2294:200V	-		BYX25/600,SSiE2040
1N2298	Si-Di	=1N2294:250V	-		BYX25/600,SSiE2040
1N2299	Si-Di	=1N2294:300V	-		BYX25/600,SSiE2040
1N23	Si-Di	UHF,X-Band-M,4V,30mA,9375MHz	Koax	Nec,Tho,++	-
1N230	Z-Di	=1N225:23,5V	2c	-	-
1N2300	Si-Di	=1N2294:350V	-		BYX25/600,SSiE2040
1N2301	Si-Di	=1N2294:400V	-		BYX25/600,SSiE2040
1N2302	Si-Di	Gl-L,50V,22A	-		BYX25/600,SSiE2040
1N2303	Si-Di	=1N2302:100V	-		BYX25/600,SSiE2040
1N2304	Si-Di	=1N2302:150V	-		BYX25/600,SSiE2040
1N2305	Si-Di	=1N2302:200V	-		BYX25/600,SSiE2040
1N2306	Si-Di	=1N2302:250V	-		BYX25/600,SSiE2040
1N2307	Si-Di	=1N2302:300V	-		BYX25/600,SSiE2040
1N2308	Si-Di	=1N2302:350V	-		BYX25/600,SSiE2040
1N2309	Si-Di	=1N2302:400V	-		BYX25/600,SSiE2040
1N231	Z-Di	=1N225:28,5V	2c	-	-
1N2310	Si-Di	Gl-L,50V,35A	-		1N3765..68,1N4525..30
1N2311	Si-Di	=1N2310:100V	-		1N3765..68,1N4525..30
1N2312	Si-Di	=1N2310:150V	-		1N3765..68,1N4525..30
1N2313	Si-Di	=1N2310:200V	-		1N3765..68,1N4525..30
1N2314	Si-Di	=1N2310:250V	-		1N3765..68,1N4526..30
1N2315	Si-Di	=1N2310:300V	-		1N3765..68,1N4526..30
1N2316	Si-Di	=1N2310:350V	-		1N3765..68,1N4526..30
1N2317	Si-Di	=1N2310:400V	-		1N3765..68,1N4526..30
1N2318	Si-Di	Gl-L,50V,35A	-		1N3765..68,1N4525..30
1N2319	Si-Di	=1N2318:100V	-		1N3765..68,1N4525..30
1N232	Z-Di	=1N225:34,5V	2c	-	-
1N2320	Si-Di	=1N2318:150V	-		1N3765..68,1N4525..30
1N2321	Si-Di	=1N2318:200V	-		1N3765..68,1N4525..30
1N2322	Si-Di	=1N2318:250V	-		1N3765..68,1N4526..30
1N2323	Si-Di	=1N2318:300V	-		1N3765..68,1N4526..30
1N2324	Si-Di	=1N2318:350V	-		1N3765..68,1N4526..30
1N2325	Si-Di	=1N2318:400V	-		1N3765..68,1N4526..30
1N2326	Ge-Di	Stabi,1V,0,2A	2c	Rca	-

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1N2327	Si-Di	GI,1100V,0,4A	34a	Sem,Ssi	BY127,BY133,BYX94..95,GP10Q,+
1N2328	Si-Di	=1N2327:2200V	34a	-	1N1732A,1N1733A
1N233	Z-Di	=1N225:41V	2c	-	-
1N234	Z-Di	=1N225:48V	2c	-	-
1N2348	Si-Di	GI-L,50V,3A(Tc=50o)	32a$	Sem,Ssi	BYX38/300,BYX39/600
1N2349	Si-Di	=1N2348:100V	32a$	-	BYX38/300,BYX39/600
1N235	Z-Di	=1N225:58V	2c	-	-
1N2350	Si-Di	=1N2348:150V	32a$	-	BYX38/300,BYX39/600
1N2357	Si-Di	GI,1400V,0,4A	34a	USA	BY231/1400,BY268..269,GP10V,+
1N2358	Si-Di	=1N2357:1500V	34a	-	BY231/1500,BY269,DM513,GP10W
1N2359	Si-Di	=1N2357:1600V	34a	-	BY269,DM513,EM516,GP10Y
1N236	Z-Di	71V,10%,0,15W	2c	-	-
1N2360	Si-Di	=1N2357:1800V	34a	-	DM516,1N1732A
1N2361	Si-Di	=1N2357:2000V	34a	-	1N1732A
1N2362	Si-Di	GI-L,1400V,1A	32a$	USA	-
1N2362A...2371A	Si-Di	=1N2362..2371:5A	32a($)	-	-
1N2362A..2371A	Si-Di	-	32a($)	-	-
1N2362B...2371B	Si-Di	=1N2362..2371:10A	32a($)	-	-
1N2362B..2371B	Si-Di	-	32a($)	-	-
1N2363	Si-Di	=1N2362:Iso	32a	-	-
1N2364	Si-Di	=1N2362:1500V	32a$	-	-
1N2365	Si-Di	=1N2362:1500V,Iso	32a	-	-
1N2366	Si-Di	=1N2362:1600V	32a$	-	-
1N2367	Si-Di	=1N2362:1600V,Iso	32a	-	-
1N2368	Si-Di	=1N2362:1800V	32a$	-	-
1N2369	Si-Di	=1N2362:1800V,Iso	32a	-	-
1N237	Z-Di	=1N236:88V	2c	-	-
1N2370	Si-Di	=1N2362:2000V	32a$	-	-
1N2371	Si-Di	=1N2362:2000V,Iso	32a	-	-
1N2372	Si-Di	GI-L,1000V,0,2A(Tc=150o)	32a$	USA	-
1N2373	Si-Di	GI,600V,0,25A	31a	USA	BY126..127,BY133..134,1N4005..07,+
1N2374	Si-Di	GI,1000V,0,25A	31a	USA	BY127,BY133,GP10Q,1N4007..07,+
1N2375	Si-Di	GI,1500V,0,2A	31a	USA	BY231/1500,BY269,DM513,GP10W
1N2376	Si-Di	GI,2000V,0,2A	31a	USA	HVG2,GP02-20,MR250-2,1N1732(A)
1N2377	Si-Di	GI,2400V,0,15A	31a	USA	HVG3,GP02-30,MR250-3,1N1733(A)
1N2378	Si-Di	GI,3000V,0,15A	31a	USA	HVG3,GP02-30,MR250-3,1N1733(A)
1N2379	Si-Di	GI,4000V,0,15A	31a	USA	HVG4,GP02-40,MR250-4,1N1734(A)
1N238	Z-Di	=1N236:105V	2c	-	-
1N2380	Si-Di	GI,6000V,0,1A	31a	USA	BYX90,1N5183
1N2381	Si-Di	GI,10kV,0,075A	31a	USA	1N3052
1N2382	Si-Di	kV-GI,4kV,0,15A	31a	Gen,Mot,++	HVG4,GP02-40,MR250-4,1N1734(A)
1N2382A	Si-Di	=1N2382:0,35A	31a	-	1N1734A
1N2383	Si-Di	kV-GI,6kV,0,1A	31a	Gen,Mot,++	BYX90,1N5183
1N2383A	Si-Di	=1N2383:0,35A	31a	-	-
1N2384	Si-Di	kV-GI,8kV,0,07A	31a	Gen,Mot,++	1N5184
1N2384A	Si-Di	=1N2384:0,275A	31a	-	-
1N2385	Si-Di	kV-GI,10kV,0,07A	31a	Gen,Mot,++	1N5184
1N2385A	Si-Di	=1N2384:0,2A	31a	-	-
1N2386	Ge-Di	UHF,5V	Koax	old	-
1N2387	Z-Di	30V,10%,1W	34a	Sem,Ssi	BZW22/C10,BZX61/C10,ZPY10,1N5925,+
1N2389	Si-Di	Dual,GI,1600V,0,6A	-	USA	-
1N239	Z-Di	=1N236:128V	2c	-	-
1N2390(A)	Si-Di	GI,50V,1,5A	-	USA	BY226..227,BY251..255,1N5391..99,+
1N2391(A)	Si-Di	=1N2390:100V	-	-	BY226..227,BY251..255,1N5392..99,+
1N2392(A)	Si-Di	=1N2390:200V	-	-	BY226..227,BY251..255,1N5393..99,+
1N2393(A)	Si-Di	=1N2390:300V	-	-	BY226..227,BY252..255,1N5394..99,+
1N2394(A)	Si-Di	=1N2390:400V	-	-	BY226..227,BY252..255,1N5395..99,+
1N2395(A)	Si-Di	=1N2390:500V	-	-	BY226..227,BY253..255,1N5396..99,+
1N2396(A)	Si-Di	=1N2390:600V	-	-	BY226..227,BY253..255,1N5397..99,+
1N2397(A)	Si-Di	=1N2390:700V	-	-	BY227,BY254..255,1N5398..99,+
1N2398(A)	Si-Di	=1N2390:800V	-	-	BY227,BY254..255,1N5398..99,+
1N2399(A)	Si-Di	=1N2390	-	-	→1N2390
1N2400(A)	Si-Di	=1N2391	-	-	→1N2391
1N2401(A)	Si-Di	=1N2392	-	-	→1N2392

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1N2402(A)	Si-Di	=1N2393	-		→1N2393
1N2403(A)	Si-Di	=1N2394	-		→1N2394
1N2404(A)	Si-Di	=1N2395	-		→1N2395
1N2405(A)	Si-Di	=1N2396	-		→1N2396
1N2406(A)	Si-Di	=1N2397	-		→1N2397
1N2407(A)	Si-Di	=1N2398	-		→1N2398
1N2408(A)	Si-Di	=1N2390	-		→1N2390
1N2409(A)	Si-Di	=1N2391	-		→1N2391
1N2410(A)	Si-Di	=1N2392	-		→1N2392
1N2411(A)	Si-Di	=1N2393	-		→1N2393
1N2412(A)	Si-Di	=1N2394	-		→1N2394
1N2413(A)	Si-Di	=1N2395	-		→1N2395
1N2414(A)	Si-Di	=1N2396	-		→1N2396
1N2415(A)	Si-Di	=1N2397	-		→1N2397
1N2416(A)	Si-Di	=1N2398	-		→1N2398
1N2417(A)	Si-Di	=1N2390	-		→1N2390
1N2418(A)	Si-Di	=1N2391	-		→1N2391
1N2419(A)	Si-Di	=1N2392	-		→1N2392
1N2420(A)	Si-Di	=1N2393	-		→1N2393
1N2421(A)	Si-Di	=1N2394	-		→1N2394
1N2422(A)	Si-Di	=1N2395	-		→1N2395
1N2423(A)	Si-Di	=1N2396	-		→1N2396
1N2424(A)	Si-Di	=1N2397	-		→1N2397
1N2425(A)	Si-Di	=1N2398	-		→1N2398
1N2426	Si-Di	GI-L,50V,100A(Tc=75o)	73a$	USA	1N3288..97
1N2427	Si-Di	=1N2326:100V	73a$	-	1N3288..97
1N2428	Si-Di	=1N2326:150V	73a$	-	1N3289..97
1N2429	Si-Di	=1N2326:200V	73a$	-	1N3289..97
1N2430	Si-Di	=1N2326:250V	73a$	-	1N3290..97
1N2431	Si-Di	=1N2326:300V	73a$	-	1N3290..97
1N2432	Si-Di	=1N2326:350V	73a$	-	1N3291..97
1N2433	Si-Di	=1N2326:400V	73a$	-	1N3291..97
1N2434	Si-Di	=1N2326:500V	73a$	-	1N3292..97
1N2435	Si-Di	=1N2326:600V	73a$	-	1N3293..97
1N2436	Si-Di	GI-L,50V,150A(Tc=75o)	73a$	USA	1N4587..96
1N2437	Si-Di	=1N2436:100V	73a$	-	1N4587..96
1N2438	Si-Di	=1N2436:150V	73a$	-	1N4588..96
1N2439	Si-Di	=1N2436:200V	73a$	-	1N4588..96
1N2440	Si-Di	=1N2436:250V	73a$	-	1N4589..96
1N2441	Si-Di	=1N2436:300V	73a$	-	1N4589..96
1N2442	Si-Di	=1N2436:350V	73a$	-	1N4590..96
1N2443	Si-Di	=1N2436:400V	73a$	-	1N4590..96
1N2444	Si-Di	=1N2436:500V	73a$	-	1N4591..96
1N2445	Si-Di	=1N2436:600V	73a$	-	1N4592..96
1N2446	Si-Di	GI-L,50V,45A(Tc=60o)	32a$	USA	-
1N2447	Si-Di	=1N2446:100V	32a$	-	-
1N2448	Si-Di	=1N2446:150V	32a$	-	-
1N2449	Si-Di	=1N2446:200V	32a$	-	-
1N2450	Si-Di	=1N2446:250V	32a$	-	-
1N2451	Si-Di	=1N2446:300V	32a$	-	-
1N2452	Si-Di	=1N2446:350V	32a$	-	-
1N2453	Si-Di	=1N2446:400V	32a$	-	-
1N2454	Si-Di	=1N2446:500V	32a$	-	-
1N2455	Si-Di	=1N2446:600V	32a$	-	-
1N2456	Si-Di	=1N2446:700V	32a$	-	-
1N2457	Si-Di	=1N2446:800V	32a$	-	-
1N2458	Si-Di	GI-L,50V,60A(Tc=60o)	32a$	USA	-
1N2459	Si-Di	=1N2458:100V	32a$	-	-
1N2460	Si-Di	=1N2458:150V	32a$	-	-
1N2461	Si-Di	=1N2458:200V	32a$	-	-
1N2462	Si-Di	=1N2458:250V	32a$	-	-
1N2463	Si-Di	=1N2458:300V	32a$	-	-
1N2464	Si-Di	=1N2458:350V	32a$	-	-
1N2465	Si-Di	=1N2458:400V	32a$	-	-

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1N2466	Si-Di	=1N2458:500V	32a$	-	-
1N2467	Si-Di	=1N2458:600V	32a$	-	-
1N2468	Si-Di	=1N2458:700V	32a$	-	-
1N2469	Si-Di	=1N2458:800V	32a$	-	-
1N248(A..C)	Si-Di	Gl-L,50(C:55)V,10(A..C:20)A	32a$	Mot,Rca,++	BYX25/600
1N248(A..C)R	Si-Di	=1N248(A..C):	32b&	-	BYX25/600R,DS17-02A,SSiE2040
1N2482	Si-Di	Gl,200V,0,75A	31a	USA	BY126..127,BY133..134,1N4003..07,+
1N2483	Si-Di	=1N2482:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N2484	Si-Di	=1N2482:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N2485	Si-Di	Gl,200V,0,75A	34a	USA	BY126..127,BY133..134,1N4003..07,+
1N2486	Si-Di	=1N2485:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2487	Si-Di	=1N2485:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2488	Si-Di	=1N2485:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2489	Si-Di	=1N2485:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N249(A..C)	Si-Di	=1N248..:100V,C:110V	32a$	Mot,Rca,++	BYX25/600
1N249(A..C)R	Si-Di	=1N249(A..C):	32b&	-	BYX25/600R,DS17-02A,SSiE2040
1N2490	Si-Di	Dual,Gl,1600V,0,5A	-	USA	-
1N2491	Si-Di	Gl-L,50V,6A(Tc=150o)	32a$	USA	BYX38/300,BYX39/600
1N2492	Si-Di	=1N2491:100V	32a$	-	BYX38/300,BYX39/600
1N2493	Si-Di	=1N2491:200V	32a$	-	BYX38/300,BYX39/600
1N2494	Si-Di	=1N2491:300V	32a$	-	BYX38/300,BYX39/600
1N2495	Si-Di	=1N2491:400V	32a$	-	BYX38/600,BYX39/600
1N2496	Si-Di	=1N2491:500V	32a$	-	BYX38/600,BYX39/600
1N2497	Si-Di	=1N2491:600V	32a$	-	BYX38/600,BYX39/600
1N2498	Z-Di	10V,10%,10W	32	USA,Mot,Sie	BZX98/..,BZY93/..,1N2974..76
1N2498A...2500A	Z-Di	=1N2498..2500:5%	32	-	-
1N2498A..2500A	Z-Di	=1N2498..2500:5%	32	-	-
1N2498C...2500C	Z-Di	=1N2498..2500:bidirektional	32	-	-
1N2498C..2500C	Z-Di	=1N2498..2500:Bidirectional	32	-	-
1N2499	Z-Di	=1N2498:11V	32	-	-
1N25	Si-Di	UHF,L-Band-M,1000MHz	Koax	USA	-
1N250(A..C)	Si-Di	=1N248..:200V,C:220V	32a$	Mot,Rca,++	BYX25/600
1N250(A..C)R	Si-Di	=1N250(A..C):	32b&	-	BYX25/600R,DS17-02A,SSiE2040
1N250(AR..CR)	Si-Di	-	32b&	-	BYX25/600R,DS17-02A,SSiE2040
1N2500	Z-Di	=1N2498:12V	32	-	-
1N2501	Si-Di	Gl,800V,0,15A	34a	USA	BA159,BAY90,BY203/12,SHG1
1N2502	Si-Di	=1N2501:1000V	34a	-	BA159,BAY90,BY203/12,SHG1
1N2503	Si-Di	=1N2501:1200V	34a	-	BAY91,BY203/12,SHG1,5
1N2504	Si-Di	=1N2501:1500V	34a	-	BAY91,BY203/15,SHG1,5
1N2505	Si-Di	Gl,800V,0,3A	34a	USA	BA159,BAY90,BY203/12,GP10Q,+
1N2506	Si-Di	=1N2505:1000V	34a	-	BA159,BAY90,BY203/12,GP10Q,+
1N2507	Si-Di	=1N2505:1200V	34a	-	BAY91,BY203/12,EM513,GP10Q,+
1N2508	Si-Di	=1N2505:1500V	34a	-	BAY91,BY203/15,EM516,GP10Y,+
1N2509	Si-Di	UHF,C-Band-M,9GHz	Koax	USA	-
1N251	Si-Di	S,40V,75mA,<150ns	31a	Sgs,Tix,++	BAV18..21,BAX15..17,1N3070,+
1N2510	Si-Di	UHF,X-Band-M,10GHz	Koax	USA	-
1N2512	Si-Di	Gl-L,100V,4A(Tc=30o)	32a$	USA	BYX38/300,BYX39/600
1N2512R...2523R	Si-Di	=1N2512..2523:	32b&	-	BYX38/..R,BYX39/..R
1N2512R..2523R	Si-Di	-	32b&	-	BYX38/..R,BYX39/..R
1N2513	Si-Di	=1N2512:200V	32a$	-	BYX38/300,BYX39/600
1N2514	Si-Di	=1N2512:300V	32a$	-	BYX38/300,BYX39/600
1N2515	Si-Di	=1N2512:400V	32a$	-	BYX38/600,BYX39/600
1N2516	Si-Di	=1N2512:500V	32a$	-	BYX38/600,BYX39/600
1N2517	Si-Di	=1N2512:600V	32a$	-	BYX38/600,BYX39/600
1N2518	Si-Di	=1N2512:Iso	32a	-	-
1N2519	Si-Di	=1N2513:Iso	32a	-	-
1N251A	Si-Di	=1N251:125V,100mA	31a	-	BAV19..21,BAX15..17,1N3070,+
1N252	Si-Di	S,20V,100mA,<150ns	31a	Sgs,Tix,++	BAV18..21,BAX15..17,1N3070,+
1N2520	Si-Di	=1N2514:Iso	32a	-	-
1N2521	Si-Di	=1N2515:Iso	32a	-	-
1N2522	Si-Di	=1N2516:Iso	32a	-	-
1N2523	Si-Di	=1N2517:Iso	32a	-	-
1N2524	Si-Di	Gl-L,50V,2,5A(Tc=150o)	32a	USA	-
1N2525	Si-Di	=1N2524:100V	32a	-	-

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1N2526	Si-Di	=1N2524:200V	32a	-	-
1N2527	Si-Di	=1N2524:300V	32a	-	-
1N2528	Si-Di	=1N2524:400V	32a	-	-
1N2529	Si-Di	=1N2524:500V	32a	-	-
1N252A	Si-Di	=1N252:125V	31a	-	BAV19..21,BAX15..17,1N3070,+
1N253	Si-Di	Gl-L,95V,1A	32a$	Ssi,Tix,++	BYX38/300,BYX39/600
1N2530	Si-Di	=1N2524:600V	32a	-	-
1N2531	Si-Di	=1N2524:700V	32a	-	-
1N2532	Si-Di	=1N2524:800V	32a	-	-
1N2533	Si-Di	=1N2524:900V	32a	-	-
1N2534	Si-Di	=1N2524:1000V	32a	-	-
1N2535	Si-Di	Gl-L,50V,2,5A(Tc=150o)	32a	USA	-
1N2536	Si-Di	=1N2535:100V	32a	-	-
1N2537	Si-Di	=1N2535:200V	32a	-	-
1N2538	Si-Di	=1N2535:300V	32a	-	-
1N2539	Si-Di	=1N2535:400V	32a	-	-
1N254	Si-Di	Gl-L,190V,0,4A	32a$	Ssi,Tix,++	BYX38/300,BYX39/600
1N2540	Si-Di	=1N2535:500V	32a	-	-
1N2541	Si-Di	=1N2535:600V	32a	-	-
1N2542	Si-Di	=1N2535:700V	32a	-	-
1N2543	Si-Di	=1N2535:800V	32a	-	-
1N2544	Si-Di	=1N2535:900V	32a	-	-
1N2545	Si-Di	=1N2535:1000V	32a	-	-
1N2546	Si-Di	Gl-L,50V,2,5A(Tc=150o)	32a	USA	-
1N2547	Si-Di	=1N2546:100V	32a	-	-
1N2548	Si-Di	=1N2546:200V	32a	-	-
1N2549	Si-Di	=1N2546:300V	32a	-	-
1N255	Si-Di	Gl-L,380V,0,4A	32a$	Ssi,Tix,++	BYX38/600,BYX39/600
1N2550	Si-Di	=1N2546:400V	32a	-	-
1N2551	Si-Di	=1N2546:500V	32a	-	-
1N2552	Si-Di	=1N2546:600V	32a	-	-
1N2553	Si-Di	=1N2546:700V	32a	-	-
1N2554	Si-Di	=1N2546:800V	32a	-	-
1N2555	Si-Di	=1N2546:900V	32a	-	-
1N2556	Si-Di	=1N2546:1000V	32a	-	-
1N2557	Si-Di	Gl-L,700V,6A(Tc=150o)	32a	USA	-
1N2558	Si-Di	=1N2557:800V	32a	-	-
1N2559	Si-Di	=1N2557:900V	32a	-	-
1N256	Si-Di	Gl-L,570V,0,2A	32a$	Ssi,Tix,++	BYX38/600,BYX39/600
1N2560	Si-Di	=1N2557:1000V	32a	-	-
1N2561	Si-Di	Gl-L,700V,6A(Tc=150o)	32a	USA	-
1N2562	Si-Di	=1N2561:800V	32a	-	-
1N2563	Si-Di	=1N2561:900V	32a	-	-
1N2564	Si-Di	=1N2561:1000V	32a	-	-
1N2565	Si-Di	Gl-L,50V,6A(Tc=150o)	32a	USA	-
1N2566	Si-Di	=1N2565:100V	32a	-	-
1N2567	Si-Di	=1N2565:200V	32a	-	-
1N2568	Si-Di	=1N2565:300V	32a	-	-
1N2569	Si-Di	=1N2565:400V	32a	-	-
1N2570	Si-Di	=1N2565:500V	32a	-	-
1N2571	Si-Di	=1N2565:600V	32a	-	-
1N2572	Si-Di	=1N2565:700V	32a	-	-
1N2573	Si-Di	=1N2565:800V	32a	-	-
1N2574	Si-Di	=1N2565:900V	32a	-	-
1N2575	Si-Di	=1N2565:1000V	32a	-	-
1N2576	Si-Di	Gl-L,50V,12A(Tc=150o)	32a	USA	-
1N2577	Si-Di	=1N2576:100V	32a	-	-
1N2578	Si-Di	=1N2576:200V	32a	-	-
1N2579	Si-Di	=1N2576:300V	32a	-	-
1N258	Si-Di	UHF,S-Band-Dem,3GHz	Koax	USA	-
1N2580	Si-Di	=1N2576:400V	32a	-	-
1N2581	Si-Di	=1N2576:500V	32a	-	-
1N2582	Si-Di	=1N2576:600V	32a	-	-
1N2583	Si-Di	=1N2576:700V	32a	-	-

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1N2584	Si-Di	=1N2576:800V	32a	-	-
1N2585	Si-Di	=1N2576:900V	32a	-	-
1N2586	Si-Di	=1N2576:1000V	32a	-	-
1N2587	Si-Di	Gl-L,50V,12A(Tc=150o)	32a	USA	-
1N2588	Si-Di	=1N2587:100V	32a	-	-
1N2589	Si-Di	=1N2587:200V	32a	-	-
1N259	Si-Di	~2x1N23gep	-		-
1N2590	Si-Di	=1N2587:300V	32a	-	-
1N2591	Si-Di	=1N2587:400V	32a	-	-
1N2592	Si-Di	=1N2587:500V	32a	-	-
1N2593	Si-Di	=1N2587:600V	32a	-	-
1N2594	Si-Di	=1N2587:700V	32a	-	-
1N2595	Si-Di	=1N2587:800V	32a	-	-
1N2596	Si-Di	=1N2587:900V	32a	-	-
1N2597	Si-Di	=1N2587:1000V	32a	-	-
1N2598	Si-Di	Gl-L,50V,12A(Tc=150o)	32a	USA	-
1N2599	Si-Di	=1N2598:100V	32a	-	-
1N26	Si-Di	UHF,K-Band-M,23,984GHz	Koax	USA	-
1N2600	Si-Di	=1N2598:200V	32a	-	-
1N2601	Si-Di	=1N2598:300V	32a	-	-
1N2602	Si-Di	=1N2598:400V	32a	-	-
1N2603	Si-Di	=1N2598:500V	32a	-	-
1N2604	Si-Di	=1N2598:600V	32a	-	-
1N2605	Si-Di	=1N2598:700V	32a	-	-
1N2606	Si-Di	=1N2598:800V	32a	-	-
1N2607	Si-Di	=1N2598:900V	32a	-	-
1N2608	Si-Di	=1N2598:1000V	32a	-	-
1N2609	Si-Di	Gl,50V,0,75A	34a	USA,Mot	BY126..127,BY133..135,1N4001..07,+
1N261	Di	400V	-		-
1N2610	Si-Di	=1N2609:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N2611	Si-Di	=1N2609:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N2612	Si-Di	=1N2609:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2613	Si-Di	=1N2609:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2614	Si-Di	=1N2609:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2615	Si-Di	=1N2609:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2616	Si-Di	=1N2609:800V	34a	-	BY127,BY133,EM513,1N4006..07,+
1N2617	Si-Di	=1N2609:1000V	34a	-	BY127,BY133,EM513,1N4007,+
1N2618	Si-Di	=1N2609:1200V	34a	-	BY127,BY133,EM513,GP10Q,+
1N2619	Si-Di	=1N2609:1500V	34a	-	BY400,BY448,DM513,EM516,GP10W
1N2620(A,B)	Ref-Di	9,3V,5%,0,75W	34a	USA,Mot,Sie	-
1N2621(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2622(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2623(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2624(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2625(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2626(A,B)	Ref-Di	9,3V,5%,0,75W	34a	-	-
1N2627	Ge-Di	UHF-Tuning,5V,1GHz,2,75pF	Koax	old	-
1N2628	Ge-Di	UHF-Tuning,5V,1GHz,2,5pF	Koax	old	-
1N2629	Ge-Di	UHF,5V	Koax	old	-
1N263	Ge-Di	UHF-M,1V,50mA,9375MHz	Koax	Miv,Nec,Pai	-
1N2630	Si-Di	Dual,kV-Gl,1500V,0,085A	-	USA	-
1N2631	Si-Di	Dual,kV-Gl,1600V,0,6A	-	USA	-
1N2632	Si-Di	Dual,kV-Gl,2800V,0,2A	-	USA	-
1N2633	Si-Di	Dual,kV-Gl,1600V,0,6A	-	USA	-
1N2634	Si-Di	Dual,kV-Gl,1600V,0,6A	-	USA	-
1N2635	Si-Di	Dual,kV-Gl,1500V,0,085A	-	USA	-
1N2636	Si-Di	Dual,kV-Gl,1500V,0,085A	-	USA	-
1N2637	Si-Di	Dual,kV-Gl,10kV,0,25A	-	USA	-
1N2638	Si-Di	Gl-Stack,100V,1,5A	-	USA	-
1N264	Si-Di	~2x1N21gep	-		-
1N2641	Si-Di	=1N2638:200V	-		-
1N2644(A)	Si-Di	=1N2638:300V	-		-
1N2647(A)	Si-Di	=1N2638:400V	-		-
1N265	Ge-Di	Uni,80V	31a	USA	AA117..118,AA132..133

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1N2650(A)	Si-Di	=1N2638:600V	-		-
1N2653(A)	Si-Di	=1N2638:800V	-		-
1N2656	Si-Di	=1N2638:1200V	-		-
1N2659	Si-Di	=1N2638:1600V	-		-
1N266	Ge-Di	Uni,50V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2662	Si-Di	=1N2638:2000V	-		-
1N2664	Si-Di	=1N2638:2400V	-		-
1N2666	Si-Di	=1N2638:3200V	-		-
1N2667	Si-Di	=1N2638:4000V	-		-
1N2668	Si-Di	=1N2638:4800V	-		-
1N2669	Si-Di	3-Ph.GI-Stack,100V,3,6A	-	USA	-
1N267	Ge-Di	Uni,30V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2673	Si-Di	=1N2669:200V	-		-
1N2677	Si-Di	=1N2669:300V	-		-
1N268	Ge-Di	Uni,30V,300mA	31a	USA	AA139,1N270
1N2681	Si-Di	=1N2669:400V	-		-
1N2685	Si-Di	=1N2669:600V	-		-
1N2687	Si-Di	=1N2669:800V	-		-
1N2689	Si-Di	=1N2669:900V	-		-
1N2690	Si-Di	=1N2669:1200V	-		-
1N2691	Si-Di	=1N2669:1600V	-		-
1N2692	Si-Di	3-Ph.GI-Stack,100V,7,2A	-	USA	-
1N2694	Si-Di	=1N2692:200V	-		-
1N2696	Si-Di	=1N2692:300V	-		-
1N2698	Si-Di	=1N2692:400V	-		-
1N270	Ge-Di	Uni,100V,60mA	31a	USA,Itt,Tho	AA117..118,AA132..133
1N2700	Si-Di	=1N2692:600V	-		-
1N2701	Si-Di	=1N2692:800V	-		-
1N2702	Si-Di	GI-Stack,100V,3A	-	USA	-
1N2705	Si-Di	=1N2702:200V	-		-
1N2708	Si-Di	=1N2702:300V	-		-
1N2711	Si-Di	=1N2702:400V	-		-
1N2714	Si-Di	=1N2702:600V	-		-
1N2717	Si-Di	=1N2702:800V	-		-
1N2720	Si-Di	=1N2702:1200V	-		-
1N2722	Si-Di	=1N2702:1600V	-		-
1N2723	Si-Di	=1N2702:2000V	-		-
1N2724	Si-Di	=1N2702:2400V	-		-
1N2725	Si-Br	GI-Stack,100V,3A	-	USA	-
1N2728	Si-Br	=1N2725:200V	-		-
1N273	Ge-Di	Uni,32V,80mA	31a	USA	AA117..118,AA132..133,1N34,1N54,+
1N2731	Si-Br	=1N2725:300V	-		-
1N2734	Si-Br	=1N2725:400V	-		-
1N2737	Si-Br	=1N2725:600V	-		-
1N2738	Si-Br	=1N2725:800V	-		-
1N2739	Si-Br	=1N2725:1200V	-		-
1N2740	Si-Br	3-Ph.GI-Stack,100V,3,6A	-	USA	-
1N2742	Si-Br	=1N2740:200V	-		-
1N2744	Si-Br	=1N2740:300V	-		-
1N2746	Si-Br	=1N2740:400V	-		-
1N2748	Si-Br	=1N2740:600V	-		-
1N2749	Si-Br	=1N2740:800V	-		-
1N2750	Si-Br	GI-Stack,100V,3A	-	USA	-
1N2753	Si-Br	=1N2750:200V	-		-
1N2756	Si-Br	=1N2750:300V	-		-
1N2759	Si-Br	=1N2750:400V	-		-
1N276	Ge-Di	Uni,S,100V,60mA,<300ns	31a	USA,Itt,Tho	AAY28,AAZ15
1N2762	Si-Br	=1N2750:600V	-		-
1N2763	Si-Br	=1N2750:800V	-		-
1N2764	Si-Br	=1N2750:1200V	-		-
1N2765(A)	Ref-Di	6,8V,5%	31a	USA	-
1N2766(A)	Ref-Di	=1N2765:13,6V	31a	-	-
1N2767(A)	Ref-Di	=1N2765:20,4V	31a	-	-
1N2768(A)	Ref-Di	=1N2765:27,2V	31a	-	-

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1N2769(A)	Ref-Di	=1N2765:34V	31a	-	-
1N277(M)	Ge-Di	Uni,100(M:125)V,50mA	31a	USA,Itt,Tho	AA117..118,AA132..133
1N2770(A)	Ref-Di	=1N2765:40,8V	31a	-	-
1N2771	Si-Di	UHF,PQ=1W(750MHz)	Koax	USA	-
1N2772	Si-Di	Gl,700V,0,75A	34a	USA	BY127,BY133,EM513,1N4006..07,+
1N2773	Si-Di	=1N2772:800V	34a	-	BY127,BY133,EM513,1N4006..07,+
1N2774	Si-Di	=1N2772:900V	34a	-	BY127,BY133,EM513,1N4007,+
1N2775	Si-Di	=1N2772:1000V	34a	-	BY127,BY133,EM513,1N4007,+
1N2776	Si-Di	=1N2772:1100V	34a	-	BY127,BY133,EM513,GP10Q,+
1N2777	Si-Di	=1N2772:1200V	34a	-	BY127,BY133,EM513,GP10Q,+
1N2778	Si-Di	=1N2772:1300V	34a	-	BY400,BY448,EM513,GP10Y,+
1N2779	Si-Di	=1N2772:1400V	34a	-	BY400,BY448,EM516,GP10Y,+
1N278	Ge-Di	Uni,58V,0,17A(ss)	31a	USA,Itt	AA117..118,AA132..134,1N34,1N54,+
1N2780	Si-Di	=1N2772:1500V	34a	-	BY400,BY448,EM516,GP10Y,+
1N2781	Si-Di	=1N2772:1600V	34a	-	BY400,BY448,EM516,GP10Y,+
1N2782	Di	UHF-Dem	-	Alp	-
1N2783	Z-Di	62V,10%,6W	-		-
1N2784	Si-Di	Gl-L,200V,22A(Tc=40o)	32a$	USA	BYX96/300
1N2785	Si-Di	=1N2784:400V	32a$	-	BYX96/600
1N2786	Si-Di	Gl-L,200V,10A	32a$	USA	BYW88/200,BYX77..81
1N2787	Si-Di	=1N2786:400V	32a$	-	BYW88/400,BYX78..81
1N2788	Si-Di	Gl-L,200V,50A(Tc=40o)	32a$	USA	-
1N2789	Si-Di	=1N2788:400V	32a$	-	-
1N279	Ge-Di	Uni,32V,70mA	31a	USA,Itt	AA117..118,AA132..134,1N34,1N54,+
1N2790	Ref-Di	8,5V,5%,1W	34a	Ssi	BZX53,1N4782
1N2791	Si-Di	Gl,S,350V	2	Ssi	BA157..159,BA199/350,BAY21,+
1N2792(A,B)	Ge-Di	UHF-M,70GHz	-	Phc	-
1N2793	Si-Di	Gl-L,50V,8,5A	32a$	USA	BYW88/50,BYX75..81
1N2794	Si-Di	=1N2793:100V	32a$	-	BYW88/100,BYX76..81
1N2795	Si-Di	=1N2793:150V	32a$	-	BYW88/200,BYX77..81
1N2796	Si-Di	=1N2793:200V	32a$	-	BYW88/200,BYX77..81
1N2797	Si-Di	=1N2793:250V	32a$	-	BYW88/300,BYX78..81
1N2798	Si-Di	=1N2793:300V	32a$	-	BYW88/300,BYX78..81
1N2799	Si-Di	=1N2793:350V	32a$	-	BYW88/400,BYX78..81
1N28	Si-Di	UHF,S-Band-Dem,9V,30mA,4000MHz	Koax	Nec	-
1N2800	Si-Di	=1N2793:400V	32a$	-	BYW88/400,BYX78..81
1N2801	Ge-Di	Gl,S,20V,<500ns	?32a	USA	-
1N2802	Si-Di	UHF,X-Band-M,9375MHz	-	USA	-
1N2803	Si-Di	Gl,400V,250A	-		-
1N2804	Z-Di	6,8V,20%,50W(Tc=75o)	23d1&	Mot,Sie,Tho	-
1N2804A..2846A	Z-Di	=1N2804..2846:10%	23d1&	-	-
1N2804B..2846B	Z-Di	=1N2804..2846:5%	23d1&	-	-
1N2804R..2846R	Z-Di	=1N2804..2846:	23c1$	-	-
1N2805	Z-Di	=1N2804:7,5V	23d1&	-	-
1N2806	Z-Di	=1N2804:8,2V	23d1&	-	-
1N2807	Z-Di	=1N2804:9,1V	23d1&	-	-
1N2808	Z-Di	=1N2804:10V	23d1&	-	-
1N2809	Z-Di	=1N2804:11V	23d1&	-	-
1N281	Ge-Di	Uni,75V,75mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N2810	Z-Di	=1N2804:12V	23d1&	-	-
1N2811	Z-Di	=1N2804:13V	23d1&	-	-
1N2812	Z-Di	=1N2804:14V	23d1&	-	-
1N2813	Z-Di	=1N2804:15V	23d1&	-	-
1N2814	Z-Di	=1N2804:16V	23d1&	-	-
1N2815	Z-Di	=1N2804:17V	23d1&	-	-
1N2816	Z-Di	=1N2804:18V	23d1&	-	-
1N2817	Z-Di	=1N2804:19V	23d1&	-	-
1N2818	Z-Di	=1N2804:20V	23d1&	-	-
1N2819	Z-Di	=1N2804:22V	23d1&	-	-
1N282	Ge-Di	Uni,15V	31a	USA	AA113..119,1N34,1N54,1N60,+
1N2820	Z-Di	=1N2804:24V	23d1&	-	-
1N2821	Z-Di	=1N2804:25V	23d1&	-	-
1N2822	Z-Di	=1N2804:27V	23d1&	-	-
1N2823	Z-Di	=1N2804:30V	23d1&	-	-

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1N2824	Z-Di	=1N2804:33V	23d1&	-	-
1N2825	Z-Di	=1N2804:36V	23d1&	-	-
1N2826	Z-Di	=1N2804:39V	23d1&	-	-
1N2827	Z-Di	=1N2804:43V	23d1&	-	-
1N2828	Z-Di	=1N2804:45V	23d1&	-	-
1N2829	Z-Di	=1N2804:47V	23d1&	-	-
1N283	Ge-Di	Uni,25V,Ifsm=0,5A	31a	USA,Itt,Tho	AA139
1N2830	Z-Di	=1N2804:50V	23d1&	-	-
1N2831	Z-Di	=1N2804:51V	23d1&	-	-
1N2832	Z-Di	=1N2804:56V	23d1&	-	-
1N2833	Z-Di	=1N2804:62V	23d1&	-	-
1N2834	Z-Di	=1N2804:68V	23d1&	-	-
1N2835	Z-Di	=1N2804:75V	23d1&	-	-
1N2836	Z-Di	=1N2804:82V	23d1&	-	-
1N2837	Z-Di	=1N2804:91V	23d1&	-	-
1N2838	Z-Di	=1N2804:100V	23d1&	-	-
1N2839	Z-Di	=1N2804:105V	23d1&	-	-
1N2840	Z-Di	=1N2804:110V	23d1&	-	-
1N2841	Z-Di	=1N2804:120V	23d1&	-	-
1N2842	Z-Di	=1N2804:130V	23d1&	-	-
1N2843	Z-Di	=1N2804:150V	23d1&	-	-
1N2844	Z-Di	=1N2804:160V	23d1&	-	-
1N2845	Z-Di	=1N2804:180V	23d1&	-	-
1N2846	Z-Di	=1N2804:200V	23d1&	-	-
1N2847(A)	Si-Di	GI-L,100V,1,5A(Tc=75o)	32a	USA	-
1N2848(A)	Si-Di	=1N2847:200V	32a	-	-
1N2849(A)	Si-Di	=1N2847:300V	32a	-	-
1N285	Ge-Di	UHF-M,75mA	-	Gen	-
1N2850(A)	Si-Di	=1N2847:400V	32a	-	-
1N2851(A)	Si-Di	=1N2847:500V	32a	-	-
1N2852(A)	Si-Di	=1N2847:600V	32a	-	-
1N2855	Si-Di	GI-L,600V,250A	-		-
1N2856	Si-Di	=1N2855:800V	-		-
1N2857	Si-Di	=1N2855:1000V	-		-
1N2858(A)	Si-Di	GI,50V,0,75..1A	34a	USA,Rca	BY126..127,BY133..135,1N4001..07,+
1N2859(A)	Si-Di	=1N2858:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N286(A)	Si-Di	UHF,X/K-Band-M,16GHz	Koax	Syl	-
1N2860(A)	Si-Di	=1N2858:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N2861(A)	Si-Di	=1N2858:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2862(A)	Si-Di	=1N2858:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N2863(A)	Si-Di	=1N2858:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2864(A)	Si-Di	=1N2858:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N2865	Si-Di	GI,1000V,0,7A	34a	Scn,Sem	BY127,BY133,GP10Q,1N4007,+
1N2866	Si-Di	=1N2865:1500V	34a	-	BY400,BY448,EM516,GP10W,+
1N2867	Si-Di	GI,1000V,0,7A	-	Scn,Sem	BY127,BY133,GP10Q,1N4007,+
1N2868	Si-Di	=1N2867:1500V	-		BY400,BY448,EM516,GP10W,+
1N287	Ge-Di	Uni,40V,60mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2878	Si-Di	GI,700V,0,25A	12a	USA,Tho	BA158..159,BAY90,BY203/12,+
1N2879	Si-Di	=1N2878:1000V	31a	-	BA159,BAY90,BY203/12,SHG1,+
1N288	Ge-Di	Uni,70V,Ifsm=0,75A	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2880	Si-Di	=1N2878:1000V	12a	-	BA159,BAY90,BY203/12,SHG1,+
1N2881	Si-Di	=1N2878:1000V	31a	-	BA159,BAY90,BY203/12,SHG1,+
1N2882	Si-Di	=1N2878:1000V	12a	-	BA159,BAY90,BY203/12,SHG1,+
1N2883	Si-Di	=1N2878:1000V	31a	-	BA159,BAY90,BY203/12,SHG1,+
1N2884	Si-Di	=1N2878:1400V	12a	-	BAY91,BY203/16,GP10W,SHG1,5,+
1N2885	Si-Di	=1N2878:1400V	31a	-	BAY91,BY203/16,GP10W,SHG1,5,+
1N2886	Si-Di	=1N2878:1500V	12a	-	BAY91,BY203/16,GP10W,SHG1,5,+
1N2887	Si-Di	=1N2878:1500V	31a	-	BAY91,BY203/16,GP10W,SHG1,5,+
1N2888	Si-Di	=1N2878:1700V	12a	-	BAY91,BY203/20,DM516,SHG2,+
1N2889	Si-Di	=1N2878:1700V	31a	-	BAY91,BY203/20,DM516,SHG2,+
1N289	Ge-Di	Uni,80V,80mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2890	Si-Di	=1N2878:2000V	12a	-	BAY91,BY203/20,SHG2,1N1732(A)
1N2891	Si-Di	=1N2878:2000V	31a	-	BAY91,BY203/20,SHG2,1N1732(A)
1N2892	Si-Di	=1N2878:2100V	12a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)

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1N2893	Si-Di	=1N2878:2100V	31a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2894	Si-Di	=1N2878:2400V	12a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2895	Si-Di	=1N2878:2400V	31a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2896	Si-Di	=1N2878:2500V	12a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2897	Si-Di	=1N2878:2500V	31a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2898	Si-Di	=1N2878:2800V	12a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2899	Si-Di	=1N2878:2800V	31a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N290	Ge-Di	Uni,100V,Ifsm=0,3A	31a	USA	AA117..118,AA132..133
1N2900	Si-Di	=1N2878:3000V	12a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2901	Si-Di	=1N2878:3000V	31a	-	GP02-30,MR250-3,SHG2,5,1N1733(A)
1N2902	Si-Di	=1N2878:3100V	12a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2903	Si-Di	=1N2878:3100V	31a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2904	Si-Di	=1N2878:3500V	12a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2905	Si-Di	=1N2878:3500V	31a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2906	Si-Di	=1N2878:3500V	12a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2907	Si-Di	=1N2878:3500V	31a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2908	Si-Di	=1N2878:3800V	12a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2909	Si-Di	=1N2878:3800V	31a	-	GP02-40,HVG4,MR250-4,1N1733(A)
1N291	Ge-Di	Uni,100V,Ifsm=0,4A	31a	USA	AA117..118,AA132..133
1N2910	Si-Di	=1N2878:4000V	12a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2911	Si-Di	=1N2878:4000V	31a	-	GP02-40,HVG4,MR250-4,1N1734(A)
1N2912	Si-Di	=1N2878:4200V	12a	-	HVG5,MR250-5,1N1734(A)
1N2913	Si-Di	=1N2878:4200V	31a	-	HVG5,MR250-5,1N1734(A)
1N2914	Si-Di	=1N2878:4500V	12a	-	HVG5,MR250-5,1N1734(A)
1N2915	Si-Di	=1N2878:4500V	31a	-	HVG5,MR250-5,1N1734(A)
1N2916	Si-Di	=1N2878:4500V:	12a	-	HVG5,MR250-5,1N1734(A)
1N2917	Si-Di	=1N2878:4500V	31a	-	HVG5,MR250-5,1N1734(A)
1N2918	Si-Di	=1N2878:5000V	12a	-	HVG5,MR250-5,1N1734(A)
1N2919	Si-Di	=1N2878:5000V	31a	-	HVG5,MR250-5,1N1734(A)
1N292	Ge-Di	Uni,70V,70mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N2920	Si-Di	=1N2878:5500V	12a	-	BYX90
1N2921	Si-Di	=1N2878:5500V	31a	-	BYX90
1N2922	Si-Di	=1N2878:6000V	12a	-	BYX90
1N2923	Si-Di	=1N2878:6000V	31a	-	BYX90
1N2924	Si-Di	=1N2878:6500V	12a	-	BYX90
1N2925	Si-Di	=1N2878:6500V	31a	-	BYX90
1N2926(A)	Si-Di	UHF,K/X-Band-Dem,16GHz	Koax	Pai,Syl	-
1N2927(A)	Si-Di	Tunnel-Di,<80pF,Up=75mV,Uv=475mV	2	Msc	-
1N2928(A)	Si-Di	Tunnel-Di,<100pF,Up=80mV,Uv=490mV	2	Msc	-
1N2929(A)	Si-Di	Tunnel-Di,<150pF,Up=80mV,Uv=500mV	2	Msc	-
1N2930(A)	Si-Di	Tunnel-Di,<250pF,Up=85mV,Uv=520mV	2	Msc	-
1N2931(A)	Si-Di	Tunnel-Di,<400pF,Up=85mV,Uv=530mV	2	Msc	-
1N2932(A)	Si-Di	Tunnel-Di,<1200pF,Up=90mV,Uv=530mV	2	Msc	-
1N2933(A)	Si-Di	Tunnel-Di,<1800pF,Up=90mV,Uv=530mV	2	Msc	-
1N2934(A)	Si-Di	Tunnel-Di,<2500pF,Up=90mV,Uv=530mV	2	Msc	-
1N2937	Z-Di	50V,15%,10W	32	USA	BZX98/C51,BZY93/C51,1N2996
1N2938	Z-Di	0,9V,15%	32	USA	-
1N2939(A)	Ge-Di	Tunnel-Di,Ip=1mA,Up=65mV,2,2GHz	2	Gen	-
1N294(A)	Ge-Di	Uni,60V,50mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N2940(A)	Ge-Di	Tunnel-Di,Ip=1mA,Up=65mV,2,2GHz	2	Gen	-
1N2941(A)	Ge-Di	Tunnel-Di,Ip=4,7mA,Up=65mV,2,6GHz	2	Gen	-
1N2942	Z-Di	8,2V,5%,50W	-	Scn	-
1N2943	Z-Di	=1N2942:9,1V	-		-
1N2944	Z-Di	=1N2942:10V	-		-
1N2945	Z-Di	=1N2942:11V	-		-
1N2946	Z-Di	=1N2942:12V	-		-
1N2947	Z-Di	=1N2942:13V	-		-
1N2948	Z-Di	=1N2942:15V	-		-
1N2949	Z-Di	=1N2942:16V	-		-
1N295(A,S,X)	Ge-Di	Uni,40(S,X:30)V,35(X:20)mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N2950	Z-Di	=1N2942:18V	-		-
1N2951	Z-Di	=1N2942:20V	-		-
1N2952	Z-Dj	=1N2942:22V	-		-
1N2953	Z-Di	=1N2942:24V	-		-

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1N2954	Z-Di	=1N2942:27V	-		-
1N2955	Z-Di	=1N2942:30V	-		-
1N2956	Z-Di	=1N2942:33V	-		-
1N2957	Z-Di	=1N2942:36V	-		-
1N2958	Z-Di	=1N2942:39V	-		-
1N2959	Z-Di	=1N2942:43V	-		-
1N296	Ge-Di	40V	-		-
1N2960	Z-Di	=1N2942:47V	-		-
1N2961	Z-Di	=1N2942:51V	-		-
1N2962	Z-Di	=1N2942:56V	-		-
1N2963	Z-Di	=1N2942:62V	-		-
1N2964	Z-Di	=1N2942:68V	-		-
1N2965	Z-Di	=1N2942:75V	-		-
1N2966	Z-Di	=1N2942:82V	-		-
1N2967	Z-Di	=1N2942:91V	-		-
1N2968	Z-Di	=1N2942:100V	-		-
1N2969(A)	Ge-Di	Tunnel-Di, Ip=2mA, Up=65mV, 2,5GHz	2	Gen	-
1N297(A)	Ge-Di	Uni, 80V, 35mA	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, +
1N2970	Z-Di	6,8V, 20%, 10W(Tc=55o)	32b&	USA, Sie, Tho	BZX98/.., BZY93/.., ZL.., ZX..
1N2970A...3015A	Z-Di	=1N2970..3015:10%	32b&	-	-
1N2970A..3015A ..	Z-Di	=1N2970..3015:10%	32b&	-	-
1N2970B...3015B	Z-Di	=1N2970..3015:5%	32b&	-	-
1N2970B..3015B ..	Z-Di	=1N2970..3015:5%	32b&	-	-
1N2970R...3015R	Z-Di	=1N2970..3015	32a$	-	-
1N2970R..3015R ..	Z-Di	=1N2970..3015	32a$	-	-
1N2971	Z-Di	=1N2970:7,5V	32b&	-	-
1N2972	Z-Di	=1N2970:8,2V	32b&	-	-
1N2973	Z-Di	=1N2970:9,1V	32b&	-	-
1N2974	Z-Di	=1N2970:10V	32b&	-	-
1N2975	Z-Di	=1N2970:11V	32b&	-	-
1N2976	Z-Di	=1N2970:12V	32b&	-	-
1N2977	Z-Di	=1N2970:13V	32b&	-	-
1N2978	Z-Di	=1N2970:14V	32b&	-	-
1N2979	Z-Di	=1N2970:15V	32b&	-	-
1N298(A)	Ge-Di	Uni, 70V, 50mA, A:30mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, +
1N2980	Z-Di	=1N2970:16V	32b&	-	-
1N2981	Z-Di	=1N2970:17V	32b&	-	-
1N2982	Z-Di	=1N2970:18V	32b&	-	-
1N2983	Z-Di	=1N2970:19V	32b&	-	-
1N2984	Z-Di	=1N2970:20V	32b&	-	-
1N2985	Z-Di	=1N2970:22V	32b&	-	-
1N2986	Z-Di	=1N2970:24V	32b&	-	-
1N2987	Z-Di	=1N2970:25V	32b&	-	-
1N2988	Z-Di	=1N2970:27V	32b&	-	-
1N2989	Z-Di	=1N2970:30V	32b&	-	-
1N299	Ge-Di	Uni, 50V	31a	Kem	AA117..118, AA132..134, 1N34, 1N54, +
1N2990	Z-Di	=1N2970:33V	32b&	-	-
1N2991	Z-Di	=1N2970:36V	32b&	-	-
1N2992	Z-Di	=1N2970:39V	32b&	-	-
1N2993	Z-Di	=1N2970:43V	32b&	-	-
1N2994	Z-Di	=1N2970:45V	32b&	-	-
1N2995	Z-Di	=1N2970:47V	32b&	-	-
1N2996	Z-Di	=1N2970:50V	32b&	-	-
1N2997	Z-Di	=1N2970:51V	32b&	-	-
1N2998	Z-Di	=1N2970:52V	32b&	-	-
1N2999	Z-Di	=1N2970:56V	32b&	-	-
1N300(A,B)	Si-Di	Uni, 15V, 65mA, A:80mA, B:100mA	31a	USA	BA127, BA147/25, 1N4148, 1N5194..96, +
1N3000	Z-Di	=1N2970:62V	32b&	-	-
1N3001	Z-Di	=1N2970:68V	32b&	-	-
1N3002	Z-Di	=1N2970:75V	32b&	-	-
1N3003	Z-Di	=1N2970:82V	32b&	-	-
1N3004	Z-Di	=1N2970:91V	32b&	-	-
1N3005	Z-Di	=1N2970:100V	32b&	-	-
1N3006	Z-Di	=1N2970:105V	32b&	-	-

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1N3007	Z-Di	=1N2970:110V	32b&	-	-
1N3008	Z-Di	=1N2970:120V	32b&	-	-
1N3009	Z-Di	=1N2970:130V	32b&	-	-
1N301(A,B)	Si-Di	Uni,70V,45(A:65,B:75)mA	-	USA	BA127,BA147/100,1N4148,1N5194..96+
1N3010	Z-Di	=1N2970:140V	32b&	-	-
1N3011	Z-Di	=1N2970:150V	32b&	-	-
1N3012	Z-Di	=1N2970:160V	32b&	-	-
1N3013	Z-Di	=1N2970:175V	32b&	-	-
1N3014	Z-Di	=1N2970:180V	32b&	-	-
1N3015	Z-Di	=1N2970:200V	32b&	-	-
1N3016	Z-Di	6,8V,20%,1W	34a	USA,Sie,Tho	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1N3016A...3051A	Z-Di	=1N3016..3051:10%	34a	-	-
1N3016A..3051A	Z-Di	=1N3016..3051:10%	34a	-	-
1N3016B...3051B	Z-Di	=1N3016..3051:5%	34a	-	-
1N3016B..3051B	Z-Di	=1N3016..3051:5%	34a	-	-
1N3017	Z-Di	=1N3016:7,5V	34a	-	-
1N3018	Z-Di	=1N3016:8,2V	34a	-	-
1N3019	Z-Di	=1N3016:9,1V	34a	-	-
1N302(A,B)	Si-Di	Uni,225V,30(A:40,B:55)mA	-	USA	BA147/230,BAY21,BAY46,1N5196,+
1N3020	Z-Di	=1N3016:10V	34a	-	-
1N3021	Z-Di	=1N3016:11V	34a	-	-
1N3022	Z-Di	=1N3016:12V	34a	-	-
1N3023	Z-Di	=1N3016:13V	34a	-	-
1N3024	Z-Di	=1N3016:15V	34a	-	-
1N3025	Z-Di	=1N3016:16V	34a	-	-
1N3026	Z-Di	=1N3016:18V	34a	-	-
1N3027	Z-Di	=1N3016:20V	34a	-	-
1N3028	Z-Di	=1N3016:22V	34a	-	-
1N3029	Z-Di	=1N3016:24V	34a	-	-
1N303(A,B)	Si-Di	Uni,125V,40(A:55,B:65)mA	31a	USA	BA147/150,BAY20,BAY45,1N5195..96+
1N3030	Z-Di	=1N3016:27V	34a	-	-
1N3031	Z-Di	=1N3016:30V	34a	-	-
1N3032	Z-Di	=1N3016:33V	34a	-	-
1N3033	Z-Di	=1N3016:36V	34a	-	-
1N3034	Z-Di	=1N3016:39V	34a	-	-
1N3035	Z-Di	=1N3016:43V	34a	-	-
1N3036	Z-Di	=1N3016:47V	34a	-	-
1N3037	Z-Di	=1N3016:51V	34a	-	-
1N3038	Z-Di	=1N3016:56V	34a	-	-
1N3039	Z-Di	=1N3016:62V	34a	-	-
1N304	Ge-Di	Uni,55V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N3040	Z-Di	=1N3016:68V	34a	-	-
1N3041	Z-Di	=1N3016:75V	34a	-	-
1N3042	Z-Di	=1N3016:82V	34a	-	-
1N3043	Z-Di	=1N3016:91V	34a	-	-
1N3044	Z-Di	=1N3016:100V	34a	-	-
1N3045	Z-Di	=1N3016:110V	34a	-	-
1N3046	Z-Di	=1N3016:120V	34a	-	-
1N3047	Z-Di	=1N3016:130V	34a	-	-
1N3048	Z-Di	=1N3016:150V	34a	-	-
1N3049	Z-Di	=1N3016:160V	34a	-	-
1N305	Ge-Di	Uni,60V,125mA,3pF	31a	USA	AA136,1N270
1N3050	Z-Di	=1N3016:180V	34a	-	-
1N3051	Z-Di	=1N3016:200V	34a	-	-
1N3052	Si-Di	kV-Gl,12kV,0,1A	31a	USA	-
1N3053	Si-Di	=1N3052:14kV	31a	-	-
1N3054	Si-Di	=1N3052:16kV	31a	-	-
1N3055	Si-Di	=1N3052:18kV	31a	-	-
1N3056	Si-Di	=1N3052:20kV	31a	-	-
1N3057	Si-Di	=1N3052:22kV	31a	-	-
1N3058	Si-Di	=1N3052:24kV	31a	-	-
1N3059	Si-Di	=1N3052:26kV	31a	-	-
1N306	Ge-Di	Uni,15V,150mA,3pF	31a	USA	AA135..136,AA139,1N270
1N3060	Si-Di	=1N3052:28kV	31a	-	-

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1N3061	Si-Di	=1N3052:30kV	31a	-	-
1N3062	Si-Di	SS,50V,0,075A,<1pF,<4ns	31a	USA,Tho	BA218,BAX13,BAX91,1N4148..49,+
1N3063	Si-Di	SS,50V,0,075A,<2pF,<4ns	31a	-	BA218,BAX13,BAX91,1N4148..49,+
1N3064	Si-Di	SS,50V,0,075A,<2pF,<4ns	31a	-	BA218,BAX13,BAX91,1N4148..49,+
1N3065	Si-Di	SS,50V,0,115A,<1,5pF,<4ns	31a	USA,Tho	BA218,BAX13,BAX91,1N4148..49,+
1N3066	Si-Di	SS,50V,0,115A,<1pF,<2ns	31a	-	BA218,BAX13,BAX91,1N4148..49,+
1N3067	Si-Di	SS,30V,0,115A,<4pF,<4ns	31a	-	BA218,BAX13,BAX91,1N4148..49,+
1N3068	Si-Di	S,30V,0,075A,<6pF,<50ns	31a	Fch,Tix,++	BAV17..21,BAX90,BAX94,BAY41,+
1N3069	Si-Di	S,65V,0,225A,<6pF,<50ns	31a	USA,Tho	BAV18..21,BAW48..50,BAY72,+
1N307	Ge-Di	Uni,125V,50mA,3pF	-	USA	AA117..118,AA132..133
1N3070	Si-Di	Uni,S,200V,0,15A,<5pF,<50ns	31a	USA,Tho	BA197..198,BAV20..21,BAW50,+
1N3071	Si-Di	S,200V,0,225A,<5pF,<50ns	31a	Fch,Tix,++	BA197..198,BAV20..21,BAW50,+
1N3072	Si-Di	Gl,50V,0,2A(Tc=150o)	34a	USA	BY126..127,BY133..135,1N4001..07,+
1N3073	Si-Di	=1N3072:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N3074	Si-Di	=1N3072:150V	34a	-	BY126..127,BY133..135,1N4003..07,+
1N3075	Si-Di	=1N3072:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N3076	Si-Di	=1N3072:250V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3077	Si-Di	=1N3072:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3078	Si-Di	=1N3072:350V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3079	Si-Di	=1N3072:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N308	Ge-Di	Uni,8V,100mA	31a	USA	AA139
1N3080	Si-Di	=1N3072:500V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N3081	Si-Di	=1N3072:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N3082	Si-Di	Gl,200V,0,5A	34a	USA	BY126..127,BY133..134,1N4003..07,+
1N3083	Si-Di	=1N3082:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3084	Si-Di	=1N3082:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N3085	Si-Di	Gl-L,100V,150A(Tc=150o)	73a$	Inr,Sem,Ssi	1N4587..96
1N3086	Si-Di	=1N3085:200V	73a$	-	1N4588..96
1N3087	Si-Di	=1N3085:300V	73a$	-	1N4589..96
1N3088	Si-Di	=1N3085:400V	73a$	-	1N4590..96
1N3089	Si-Di	=1N3085:500V	73a$	-	1N4591..96
1N309	Ge-Di	Uni,30V,100mA	31a	USA	AA135..136,AA139,1N270
1N3090	Si-Di	=1N3085:600V	73a$	-	1N4592..96
1N3091	Si-Di	=1N3085:800V	73a$	-	1N4593..96
1N3092	Si-Di	=1N3085:1000V	73a$	-	1N4594..96
1N3093	Ge-Di	UHF,X-Band-S	-		-
1N3097	Ge-Di	Uni,S,30V,0,05A,<500ns	31a	Idc,Sem	AAY49,AAZ15,AAZ17,1N276
1N3098	Z-Di	120V,20%,1W	34a	Sem,Ssi	BZW22/..,BZX61/..,ZPY..,1N5951..56,+
1N3098A...3101A	Z-Di	=1N3098..3101:10%	34a	-	-
1N3098A..3101A..	Z-Di	=1N3098..3101:10%	34a	-	-
1N3099	Z-Di	=1N3098:145V	34a	-	-
1N31(A)	Si-Di	UHF,X-Band-Dem,9375MHz	Koax	USA	-
1N310	Ge-Di	Uni,100V,40mA	31a	USA	AA117..118,AA132..133
1N3100	Z-Di	=1N3098:180V	34a	-	-
1N3101	Z-Di	=1N3098:220V	34a	-	-
1N3102	Z-Di	120V,10%,10W	32	Scn	BZX98/..,BZY93/..,ZX..,1N3008..15
1N3102A...3105A	Z-Di	=1N3102..3105:5%	32	-	-
1N3102A..3105A..	Z-Di	=1N3102..3105:5%	32	-	-
1N3103	Z-Di	=1N3102:150V	32	-	-
1N3104	Z-Di	=1N3102:180V	32	-	-
1N3105	Z-Di	=1N3102:220V	32	-	-
1N3106	Si-Di	Gl,800V,0,75A	34a	Scn,Sem	BY127,BY133,BYX94..95,1N4006..07+
1N3107	Si-Di	=1N3106:1200V,0,5A	34a	-	BY127,BY133,BYX94..95,GP10Q,+
1N3108	Si-Di	Gl,800V,1,5A	32	Scn,Sem	BY227,BY254..255,1N5062,1N5398,+
1N3109	Si-Di	=1N3108:1200V,0,7A	32	-	BY227,BY255,BY350/1300,GH3E,+
1N311	Si-Di	UHF-M,9,5GHz	-		-
1N3110	Ge-Di	S,12V,0,05A	31a	USA	AAY27,AAZ18,1N3592
1N3111	Si-Di	Gl-L,50V,150A(Tc=150o)	73a$	Inr,Ssi	1N4587..96
1N3112	Z-Di	7,4V,5%,1W	34a	Sem	BZW22/C7V5,BZX61/C7V5,ZPY7,5,1N5922+
1N3113	GaAs-Di	Tunnel-Di,<10pF,Ip=1mA,Ip/Iv>10	34a	Gen	-
1N3114	GaAs-Di	Tunnel-Di,<10pF,Ip=2,2mA,Ip/Iv>10	34a	Gen	-
1N3115	GaAs-Di	Tunnel-Di,<10pF,Ip=2,2mA,Ip/Iv>10	34a	Gen	-
1N3116	GaAs-Di	Tunnel-Di,<15pF,Ip=4,7mA,Ip/Iv>10	34a	Gen	-
1N3117	GaAs-Di	Tunnel-Di,<15pF,Ip=4,7mA,Ip/Iv>9	34a	Gen	-

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1N3118	GaAs-Di	Tunnel-Di, <20pF, Ip=10mA, Ip/Iv>10	34a	Gen	-
1N3119	GaAs-Di	Tunnel-Di, <20pF, Ip=10mA, Ip/Iv>10	34a	Gen	-
1N312	Ge-Di	Uni, 50V, 70mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, +
1N3120	GaAs-Di	Tunnel-Di, Ip=22mA, Ip/Iv>10	34a	Gen	-
1N3121	Ge-Di	Uni, S, 50V, 0,11A, <4pF, <500ns	31a	USA	AAZ15, AAZ17
1N3122	Ge-Di	S, 20V, 0,18A, 1,8pF, <3500ns	31a	USA	AA139, AAZ18
1N3123	Si-Di	SS, 40V, 0,05A, <0,8pF, <4ns	31a	USA	BA218, BAX13, BAX91, 1N4148..49, +
1N3124	Si-Di	SS, 40V, 0,05A, <2pF, <4ns	31a	-	BA218, BAX13, BAX91, 1N4148..49, +
1N3125	Ge-Di	S, 55V, 300ns	31a	USA	AAY28, 1N631, 1N633
1N3128	Ge-Di	Tunnel-Di, 10mA, Up<80mV, Uv>280mV	-	Kmc, Rca	-
1N3129	Ge-Di	Tunnel-Di, 35mA, Up<100mV, Uv>300mV	-	Kmc, Rca	-
1N313	Ge-Di	Uni, 100V, 40mA	31a	USA	AA117..118, AA132..133
1N3130	Ge-Di	Tunnel-Di, 85mA, Up>120mV, Uv>350mV	-	Kmc, Rca	-
1N3138	GaAs-Di	Tunnel-Di, 100mA, Up<260mV, Up>510mV	-	Kmc, Rca	-
1N3139	Si-Di	Gl-L, 50V, 70A(Tc=150o)	32	Edi, Sem	-
1N314	Ge-Di	Uni, 75V, 100mA	31a	USA	1N270
1N3140	Si-Di	=1N3139: 100V	32	-	-
1N3141	Si-Di	=1N3139: 150V	32	-	-
1N3142	Si-Di	=1N3139: 200V	32	-	-
1N3143	Si-Di	UHF, C/X-Band-Dem, 9375MHz	Koax	USA	-
1N3144	Ge-Di	S, 20V, 500ns	-		AAY49, AAZ15, AAZ17, 1N276
1N3145	Si-Di	=1N3161: 250V	73a$	-	1N3737..44
1N3145	Ge-Di	Uni, 65V	-		AA117..118, AA132..134
1N3146	Ge-Di	SS, 25V, <2pF, <2ns	31a	USA	-
1N3147	Si-Di	Uni, 60V	31a	Sem	BA127, BA187..190, BAY19..21, +
1N3148	Ref-Di	8,5V, 0,4W	34a	Idc, Sem	1N4779, 1N4784
1N3149(A)	Ge-Di	Tunnel-Di, Ip=10mA, Up=65mV, 2,6GHz	-	Gen	-
1N315(A)	Ge-Di	Gl, 300V, 75mA, A: 200V, 100mA	34a	Gen, Spe, Ssi	-
1N3150	Ge-Di	Tunnel-Di, Ip=22mA, Up=65mV, 2,2GHz	-	Gen	-
1N3151	Si-Di	kV-Gl, 7,2kV, 0,1A	31a	Sem	BYX90, 1N5183
1N3152	Si-Di	UHF, 36GHz	-	Wes	-
1N3153	Si-Di	UHF, 36GHz	-	Wes	-
1N3154(A)	Ref-Di	8,4V, 5%, 0,4W	31a	USA, Sie, Tho	BZX51, 1N4775, 1N4780
1N3155(A)	Ref-Di	8,4V, 5%, 0,4W	31a	-	BZX52, 1N4776, 1N4781
1N3156(A)	Ref-Di	8,4V, 5%, 0,4W	31a	-	BZX53, 1N4777, 1N4781
1N3157(A)	Ref-Di	8,4V, 5%, 0,4W	31a	-	BZX54, 1N4778, 1N4783
1N3159	Ge-Di	S, 15V, 0,08A, <300ns	31a	USA	AAY27..28, AAZ18, 1N631, 1N633
1N316(A)	Si-Di	Gl, 50V, 0,25A	34a	USA	BA157..159, BAY18..21, BAY86..90, +
1N3160	Ge-Di	Uni, 60V, 0,03A	31a	Sem	AAY27..28, AAZ18, 1N631, 1N633
1N3161	Si-Di	Gl-L, 50V, 175A(Tc=150o)	73a$	USA	1N3735..44
1N3161R...3177R	Si-Di	=1N3161..3177:	73b&	-	1N3735R..3744R
1N3161R..3177R	Si-Di	-	73b&	-	1N3735R..3744R
1N3162	Si-Di	=1N3161: 100V	73a$	-	1N3735..44
1N3163	Si-Di	=1N3161: 150V	73a$	-	1N3736..44
1N3164	Si-Di	=1N3161: 200V	73a$	-	1N3736..44
1N3166	Si-Di	=1N3161: 300V	73a$	-	1N3737..44
1N3167	Si-Di	=1N3161: 350V	73a$	-	1N3738..44
1N3168	Si-Di	=1N3161: 400V	73a$	-	1N3738..44
1N3169	Si-Di	=1N3161: 500V	73a$	-	1N3739..44
1N317(A)	Si-Di	=1N316: 100V	34a	USA	BA157..159, BAY19..21, BAY87..90, +
1N3170	Si-Di	=1N3161: 600V	73a$	-	1N3740..44
1N3171(A)	Si-Di	=1N3161: 700V, 240A	73a$	-	1N3741..44
1N3172(A)	Si-Di	=1N3161: 800V, 240A	73a$	-	1N3741..44
1N3173(A)	Si-Di	=1N3161: 900V, 240A	73a$	-	1N3742..44
1N3174(A)	Si-Di	=1N3161: 1000V, 240A	73a$	-	1N3742..44
1N3175(A)	Si-Di	=1N3161: 1200V, 240A	73a$	-	1N3743..44
1N3176(A)	Si-Di	=1N3161: 1200V, 240A	73a$	-	1N3744
1N3177(A)	Si-Di	=1N3161: 1600V, 240A	73a$	-	-
1N3179	Si-Di	Gl, Uni, 240V	31a	Sem, Trw	BY126..127, BY133..134, 1N4004..07, +
1N318(A)	Si-Di	=1N316: 200V	34a	USA	BA157..159, BAY21, BAY88..90, +
1N3180	Si-Di	Gl, Uni, 130V	31a	Sem, Trw	BY126..127, BY133..135, 1N4003..07, +
1N3181	Z-Di	bidirektional, 7,7V, 10%, 0,6W	12	Idc, Sty	-
1N3182	Si-Di	VHF-Tuning, 20V, 33pF(4V), <3e(50MHz)	31a	USA	-
1N3183	Si-Br	Gl, 350V, 0,5A	79	Scn	B350C500

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1N3184	Si-Br	=1N3183:500V	79	-	B500C500
1N3185	Si-Br	=1N3183:700V	79	-	B700C500
1N3186	Si-Br	=1N3183:1000V	79	-	B1000C500
1N3187	Si-Br	=1N3183:1500V	79	-	B1500C500
1N3188	Si-Br	=1N3183:2000V	79	-	B2000C500
1N3189	Si-Di	Gl,200V,1A	34a	USA,Mot,Tho	BY226..227,BY251..255,1N5393..99,+
1N319(A)	Si-Di	=1N316:350V	34a	USA	BA157..159,BAY21,BAY88..90,+
1N3190	Si-Di	=1N3189:400V	34a	-	BY226..227,BY252..255,1N5395..99,+
1N3191	Si-Di	=1N3189:600V	34a	-	BY226..227,BY253..255,1N5397..99,+
1N3192	Si-Di	200V	-	Wes	-
1N3193	Si-Di	Gl,200V,0,75A	34a	USA,Rca,Tos	BY126..127,BY133..134,1N4003..07,+
1N3194	Si-Di	=1N3193:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3195	Si-Di	=1N3193:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N3196	Si-Di	=1N3193:800V	34a	-	BY127,BY133,BY227,1N4006..07,+
1N3197	Ge-Di	S,30V,0,08A,<300ns	31a	USA	AAY49,AAZ15,AAZ17
1N3198	Z-Di	2,25V,2%,0,4W	31a	Idc,Sem	-
1N3199	Ref-Di	8,4V,5%,0,27W	31a	Idc,Sem	BZX52,1N4776,1N4781
1N32(A)	Si-Di	UHF,S-Band-Dem,3295MHz	Koax	USA	-
1N320(A)	Si-Di	=1N316:500V	34a	USA	BA158..159,BAY89..90
1N3200	Ref-Di	8,4V,5%,0,27W	31a	-	BZX53,1N4777,1N4782
1N3201	Ref-Di	8,4V,5%,0,27W	31a	-	BZX53,1N4777,1N4782
1N3202	Ref-Di	8,4V,5%,0,27W	31a	-	BZX54,1N4778,1N4783
1N3203	Ge-Di	S,25V,0,06A,300ns	31a	USA	AAY49,AAZ15,AAZ17,1N276
1N3204	Ge-Di	S,60V,0,06A,300ns	31a	USA	AAY28,AAZ15,AAZ17,1N276
1N3205	Si-Di	UHF,Ku-Band-M,16GHz	Koax	USA	-
1N3206	Si-Di	Min,SS,100V,0,075A,<4pF,<4ns	31a	USA	(BA219,BAX96)
1N3207	Si-Di	Min,SS,60V,<9pF,<6ns	31a	USA	(BAW62,BAX95,1N4148..49,1N4151,++)
1N3208	Si-Di	Gl-L,50V,15A(Tc=150o)	32a$	USA,Mot	1N4525..30
1N3208R...3214R	Si-Di	=1N3208..3214:	32b&	-	D24C/..
1N3208R..3214R ..	Si-Di	-	32b&	-	D24C/..
1N3209	Si-Di	=1N3208:100V	32a$	-	1N4525..30
1N321(A)	Si-Di	=1N316:850V	34a	USA	BA159,BAY90..91
1N3210	Si-Di	=1N3208:200V	32a$	-	1N4525..30
1N3211	Si-Di	=1N3208:300V	32a$	-	1N4526..30
1N3212	Si-Di	=1N3208:400V	32a$	-	1N4526..30
1N3213	Si-Di	=1N3208:500V	32a$	-	1N4527..30
1N3214	Si-Di	=1N3208:600V	32a$	-	1N4527..30
1N3215	Si-Di	S,60V,<250ns	31a	-	BAW21,BAX15..17,1N4148..49,+
1N3217	Ge-Di	Tunnel-Di,<8pF,Ip=0,47mA,Ip/Iv>4,7	-	Gen	-
1N3218(A)	Ge-Di	Tunnel-Di,<10(A:<5)pF,Ip=1mA,Ip/Iv>5	-	Gen	-
1N3219(A)	Ge-Di	Tunnel-Di,<20(A:<10)pF,Ip=2,2mA	-	Gen	-
1N322(A)	Si-Di	=1N316:1000V	34a	USA	BA159,BAY90..91
1N3220	Ge-Di	Tunnel-Di,<30pF,Ip=4,7mA,Ip/Iv>4,7	-	Gen	-
1N3221(A)	Ge-Di	Ip/Iv>5,A:<35pF,Ip/Iv>6	-		-
1N3221(A)	Ge-Di	Tunnel-Di,<100pF,Ip=10mA,Up=65mV	-	Gen	-
1N3222	Ge-Di	Tunnel-Di,<150pF,Ip=22mA,Ip/Iv>5,1	-	Gen	-
1N3223	Si-Di	S,150V,2,5pF,800ns	31a	USA	BA196..198,BAV20..21,BAX15..17,+
1N3225	Ge-Di	S,40V,0,03A,<500ns	31a	Idc,Sem	AAY28,1N276,1N631,1N633
1N3227	Si-Di	Gl,Uni,100V,0,5A	31a	Idc,Sem	BY126..127,BY133..135,1N4002..07,+
1N3228	Si-Di	=1N3227:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N3229	Si-Di	=1N3227:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N323(A)	Si-Di	Gl,50V,0,4A	34a	USA	BA157..159,BY126..127,1N4001..07,+
1N3230	Si-Di	=1N3227:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3231	Si-Di	=1N3227:800V	31a	-	BY127,BY133,GP10Q,1N4006..07,+
1N3232	Si-Di	=1N3227:1000V	31a	-	BY127,BY133,GP10Q,1N4007,+
1N3233	Si-Di	=1N3227:1200V	31a	-	BY127,BY133,EM513,GP10Q,+
1N3234	Si-Di	=1N3227:1500V	31a	-	BY269,GP10W,DM513,EM516,+
1N3235	Si-Di	=1N3227:1800V	31a	-	DM516
1N3236	Si-Di	=1N3227:2000V	31a	-	-
1N3237	Si-Di	Gl,Uni,50V,0,75A	31a	USA	BY126..127,BY133..135,1N4001..07,+
1N3238	Si-Di	=1N3237:100V	31a	-	BY126..127,BY133..135,1N4002..07,+
1N3239	Si-Di	=1N3237:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N324(A)	Si-Di	=1N323:100V	34a	USA	BA157..159,BY126..127,1N4002..07,+
1N3240	Si-Di	=1N3237:400V	31a	-	BY126..127,BY133..134,1N4004..07,+

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1N3241	Si-Di	=1N3237:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3242	Si-Di	=1N3237:800V	31a	-	BY127,BY133,GP10Q,1N4006..07,+
1N3243	Si-Di	=1N3237:1000V	31a	-	BY127,BY133,GP10Q,1N4007,+
1N3244	Si-Di	=1N3237:1200V	31a	-	BY127,BY133,EM513,GP10Q,+
1N3245	Si-Di	=1N3237:1500V	31a	-	BY269,DM513,EM516,GP10W,+
1N3246	Si-Di	Gl,Uni,50V,1A	31a	USA	BY126..127,BY133..135,1N4001..07,+
1N3247	Si-Di	=1N3246:100V	31a	-	BY126..127,BY133..135,1N4002..07,+
1N3248	Si-Di	=1N3246:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N3249	Si-Di	=1N3246:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3250(A)	Si-Di	=1N323:200V	34a	USA	BA157..159,BY126..127,1N4003..07,+
1N3250	Si-Di	=1N3246:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3251	Si-Di	=1N3246:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N3252	Si-Di	=1N3246:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N3253	Si-Di	=1N3193:Iso	34a	USA,Rca,Tos	→1N3193
1N3254	Si-Di	=1N3194:Iso	34a	-	→1N3194
1N3255	Si-Di	=1N3195:Iso	34a	-	→1N3195
1N3256	Si-Di	=1N3196:Iso	34a	-	→1N3196
1N3257	Si-Di	SS,80V,<2pF,<3ns	31a	USA	BA219,BAW62,BAX95,1N4148..49,+
1N3258	Si-Di	SS,80V,<4pF,<4ns	31a	USA	BA219,BAW62,BAX95,1N4148..49,+
1N3260(A)	Si-Di	=1N323:350V	34a	USA	BA157..159,BY126..127,1N4004..07,+
1N3260	Si-Di	Gl-L,50V,160A(Tc=125o)	73a$	USA,Gen	1N4587..96
1N3260R...3276R	Si-Di	=1N3260..3276:	73b&	-	1N4587R..4596R
1N3260R..3276R	Si-Di	-	73b&	-	1N4587R..4596R
1N3261	Si-Di	=1N3260:100V	73a$	-	1N4587..96
1N3262	Si-Di	=1N3260:150V	73a$	-	1N4588..96
1N3263	Si-Di	=1N3260:200V	73a$	-	1N4588..96
1N3264	Si-Di	=1N3260:250V	73a$	-	1N4589..96
1N3265	Si-Di	=1N3260:300V	73a$	-	1N4589..96
1N3266	Si-Di	=1N3260:350V	73a$	-	1N4590..96
1N3267	Si-Di	=1N3260:400V	73a$	-	1N4590..96
1N3268	Si-Di	=1N3260:500V	73a$	-	1N4591..96
1N3269	Si-Di	=1N3260:600V	73a$	-	1N4592..96
1N327(A)	Si-Di	=1N323:500V	34a	USA	BA158..159,BY126..127,1N4005..07,+
1N3270	Si-Di	=1N3260:700V	73a$	-	1N4593..96
1N3271	Si-Di	=1N3260:800V	73a$	-	1N4593..96
1N3272	Si-Di	=1N3260:900V	73a$	-	1N4594..96
1N3273	Si-Di	=1N3260:1000V	73a$	-	1N4594..96
1N3274	Si-Di	=1N3260:1200V	73a$	-	1N4595..96
1N3275	Si-Di	=1N3260:1400V	73a$	-	1N4596
1N3276	Si-Di	=1N3260:1600V	73a$	-	-
1N3277	Si-Di	Gl,Uni,200V,0,75A	31a	USA	BY126..127,BY133..134,1N4003..07,+
1N3278	Si-Di	=1N3277:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3279	Si-Di	=1N3277:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N328(A)	Si-Di	=1N323:850V	34a	USA	BA159,BY127,BY133,1N4007,+
1N3280	Si-Di	=1N3278:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N3281	Si-Di	=1N3278:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N3282	Si-Di	Gl,Uni,1000V,0,1A	31a	USA,Mot,Tho	BY203/12,RGP01-10,SHG1,1N5181,+
1N3283	Si-Di	=1N3282:1500V	31a	-	BY203/16,RGP01-16,SHG1,5,1N5181,+
1N3284	Si-Di	=1N3282:2000V	31a	-	BY203/20,HVG2,SHG2,1N5181,+
1N3285	Si-Di	=1N3282:2500V	31a	-	HVG3,SHG2,5,1N1733,1N5181,+
1N3286	Si-Di	=1N3282:3000V	31a	-	HVG3,GP02-30,1N1733,1N5181,+
1N3287(W)	Ge-St	0,26V(1mA),0,25W	31a	USA,Itt	-
1N3288(A)	Si-Di	Gl-L,100V,100A(Tc=130o)	73a$	Gen,Inr,++	-
1N3288R...3297R	Si-Di	=1N3288..3297:	73b&	-	DS85-01C..-12C
1N3288R..3297R	Si-Di	-	73b&	-	DS85-01C..-12C
1N3289(A)	Si-Di	=1N3288:200V	73a$	-	-
1N329(A)	Si-Di	=1N323:1000V	34a	USA	BA159,BY127,BY133,1N4007,+
1N3290(A)	Si-Di	=1N3288:300V	73a$	-	-
1N3291(A)	Si-Di	=1N3288:400V	73a$	-	-
1N3292(A)	Si-Di	=1N3288:500V	73a$	-	-
1N3293(A)	Si-Di	=1N3288:600V	73a$	-	-
1N3294(A)	Si-Di	=1N3288:800V	73a$	-	-
1N3295(A)	Si-Di	=1N3288:1000V	73a$	-	-
1N3296(A)	Si-Di	=1N3288:1200V	73a$	-	-

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1N3297(A)	Si-Di	=1N3288:1400V	73a$	-	-
1N3298	Si-Di	S,60V,7pF,<200ns	31a	USA	BAV18..21,BAX15..17,BAY42..43,+
1N3298A	Si-Di	=1N3288:70V,0,3A,5pF,<20ns	31a	-	BAV18..21,BAX15..17,BAY42..43,+
1N3299	Trigger-Di	Ub=36..44V,Ib<0,125mA,Itsm=10A	31a	Mdc,Spe	-
1N330	Si-Di	Uni,32V	31a	USA	BA127..128,BA147/50,BA222,+
1N3300	Trigger-Di	Ub=14,4..21,6V,Ib<1?A,Itsm=50A	31a	Mdc,Spe	-
1N3300A	Trigger-Di	=1N3300:Ub=16,2..19,8V	31a	-	-
1N3301	Trigger-Di	=1N3300:Ub=17,6..29,4V	31a	-	-
1N3301A	Trigger-Di	=1N3300:Ub=19,8..24,2V	31a	-	-
1N3302	Trigger-Di	=1N3300:Ub=21,6..32,4V	31a	-	-
1N3302A	Trigger-Di	=1N3300:Ub=24,3..29,7V	31a	-	-
1N3303	Trigger-Di	=1N3300:Ub=26,4..39,6V	31a	-	-
1N3303A	Trigger-Di	=1N3300:Ub=29,7..36,3V	31a	-	-
1N3304	Trigger-Di	=1N3300:Ub=31,2..46,8V	31a	-	-
1N3304A	Trigger-Di	=1N3300:Ub=35,1..42,9V	31a	-	-
1N3305	Z-Di	6,8V,20%,50W(Tc=75o)	32b&	USA,Sie,Tho	BZY91/..
1N3305A...3350A	Z-Di	=1N3305..3350:10%	32b&	-	-
1N3305A..3350A..	Z-Di	=1N3305..3350:10%	32b&	-	-
1N3305B...3350B	Z-Di	=1N3305..3350:5%	32b&	-	-
1N3305B..3350B..	Z-Di	=1N3305..3350:5%	32b&	-	-
1N3305R...3350R	Z-Di	=1N3305..3350:	32a$	-	-
1N3305R..3350R..	Z-Di	=1N3305..3350:	32a$	-	-
1N3306	Z-Di	=1N3305:7,5V	32b&	-	-
1N3307	Z-Di	=1N3305:8,2V	32b&	-	-
1N3308	Z-Di	=1N3305:9,1V	32b&	-	-
1N3309	Z-Di	=1N3305:10V	32b&	-	-
1N331	Si-Di	Uni,16V	31a	USA	BA127..128,BA147/25,BA222,+
1N3310	Z-Di	=1N3305:11V	32b&	-	-
1N3311	Z-Di	=1N3305:12V	32b&	-	-
1N3312	Z-Di	=1N3305:13V	32b&	-	-
1N3313	Z-Di	=1N3305:14V	32b&	-	-
1N3314	Z-Di	=1N3305:15V	32b&	-	-
1N3315	Z-Di	=1N3305:16V	32b&	-	-
1N3316	Z-Di	=1N3305:17V	32b&	-	-
1N3317	Z-Di	=1N3305:18V	32b&	-	-
1N3318	Z-Di	=1N3305:19V	32b&	-	-
1N3319	Z-Di	=1N3305:20V	32b&	-	-
1N332	Si-Di	GI-L,400V,1,2A	32a$	USA	BYX38/600,BYX39/600
1N3320	Z-Di	=1N3305:22V	32b&	-	-
1N3321	Z-Di	=1N3305:24V	32b&	-	-
1N3322	Z-Di	=1N3305:25V	32b&	-	-
1N3323	Z-Di	=1N3305:27V	32b&	-	-
1N3324	Z-Di	=1N3305:30V	32b&	-	-
1N3325	Z-Di	=1N3305:33V	32b&	-	-
1N3326	Z-Di	=1N3305:36V	32b&	-	-
1N3327	Z-Di	=1N3305:39V	32b&	-	-
1N3328	Z-Di	=1N3305:43V	32b&	-	-
1N3329	Z-Di	=1N3305:45V	32b&	-	-
1N333	Si-Di	=1N332:0,6A	32a$	USA	BYX38/600,BYX39/600
1N3330	Z-Di	=1N3305:47V	32b&	-	-
1N3331	Z-Di	=1N3305:50V	32b&	-	-
1N3332	Z-Di	=1N3305:51V	32b&	-	-
1N3333	Z-Di	=1N3305:52V	32b&	-	-
1N3334	Z-Di	=1N3305:56V	32b&	-	-
1N3335	Z-Di	=1N3305:62V	32b&	-	-
1N3336	Z-Di	=1N3305:68V	32b&	-	-
1N3337	Z-Di	=1N3305:75V	32b&	-	-
1N3338	Z-Di	=1N3305:82V	32b&	-	-
1N3339	Z-Di	=1N3305:91V	32b&	-	-
1N334	Si-Di	=1N332:300V	32a$	USA	BYX38/300,BYX39/600
1N3340	Z-Di	=1N3305:100V	32b&	-	-
1N3341	Z-Di	=1N3305:105V	32b&	-	-
1N3342	Z-Di	=1N3305:110V	32b&	-	-
1N3343	Z-Di	=1N3305:120V	32b&	-	-

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1N3344	Z-Di	=1N3305:130V	32b&	-	-
1N3345	Z-Di	=1N3305:140V	32b&	-	-
1N3346	Z-Di	=1N3305:150V	32b&	-	-
1N3347	Z-Di	=1N3305:160V	32b&	-	-
1N3348	Z-Di	=1N3305:175V	32b&	-	-
1N3349	Z-Di	=1N3305:180V	32b&	-	-
1N335	Si-Di	=1N332:300V,0,6A	32a$	USA	BYX38/300,BYX39/600
1N3350	Z-Di	=1N3305:200V	32b&	-	-
1N3353	Ge-Di	Backward-Di,4pF,Ip=100?A	2	Phc	-
1N3354	Si-Di	GI,10V,3A(Tc=55o)	32	Cri	BYX38/300,BYX39/600
1N3355	Si-Di	=1N3354:15V	32	-	BYX38/300,BYX39/600
1N3356	Si-Di	=1N3354:25V	32	-	BYX38/300,BYX39/600
1N3357	Si-Di	=1N3354:50V	32	-	BYX38/300,BYX39/600
1N3358	Si-Di	=1N3354:75V	32	-	BYX38/300,BYX39/600
1N3359	Si-Di	=1N3354:100V	32	-	BYX38/300,BYX39/600
1N336	Si-Di	=1N332:200V	32a$	USA	BYX38/300,BYX39/600
1N3360	Si-Di	=1N3354:150V	32	-	BYX38/300,BYX39/600
1N3361	Si-Di	=1N3354:200V	32	-	BYX38/300,BYX39/600
1N3362	Si-Di	=1N3354:300V	32	-	BYX38/300,BYX39/600
1N3363	Si-Di	=1N3354:400V	32	-	BYX38/600,BYX39/600
1N3364	Si-Di	=1N3354:500V	32	-	BYX38/600,BYX39/600
1N3365	Si-Di	=1N3354:600V	32	-	BYX38/600,BYX39/600
1N3366	Si-Di	=1N3354:700V	32	-	BYX38/900,BYX39/800
1N3367	Si-Di	=1N3354:800V	32	-	BYX38/900,BYX39/800
1N3368	Si-Di	=1N3354:900V	32	-	BYX38/900,BYX39/1000
1N3369	Si-Di	=1N3354:1000V	32	-	BYX38/1200,BYX39/1000
1N337	Si-Di	=1N332:200V,0,6A	32a$	USA	BYX38/300,BYX39/600
1N3370	Si-Di	=1N3354:1200V	32	-	BYX38/1200,BYX39/1200
1N3371	Si-Di	=1N3354:1500V	32	-	-
1N3372	Si-Di	GI-L,10V,20A(Tc=100o)	75	Cri	DS25-01A,1N3491..95
1N3373	Si-Di	=1N3372:25V	75	-	DS25-01A,1N3491..95
1N3374	Si-Di	=1N3372:50V	75	-	DS25-01A,1N3491..95
1N3375	Si-Di	=1N3372:100V	75	-	DS25-01A,1N3492..95
1N3376	Si-Di	=1N3372:150V	75	-	DS25-02A,1N3493..95
1N3377	Si-Di	=1N3372:200V	75	-	DS25-02A,1N3493..95
1N3378	Si-Di	=1N3372:300V	75	-	DS25-03A,1N3494..95
1N3379	Si-Di	=1N3372:400V	75	-	DS25-05A,1N3495
1N338	Si-Di	GI-L,100V,3A	32a$	USA	BYX38/300,BYX39/600
1N3380	Si-Di	=1N3372:500V	75	-	DS25-05A
1N3381	Si-Di	GI,15V	-	Cri	-
1N3382	Si-Di	=1N3381:30V	-		-
1N3383	Si-Di	=1N3381:50V	-		-
1N3384	Si-Di	=1N3381:75V	-		-
1N3385	Si-Di	=1N3381:100V	-		-
1N3386	Si-Di	=1N3381:150V	-		-
1N3387	Si-Di	=1N3381:200V	-		-
1N3388	Si-Di	=1N3381:250V	-		-
1N3389	Si-Di	=1N3381:300V	-		-
1N339	Si-Di	=2N338:1,2A	32a$	USA	BYX38/300,BYX39/600
1N3390	Si-Di	=1N3381:400V	-		-
1N3391	Si-Di	=1N3381:500V	-		-
1N3392	Z-Di	1,5V,10%,0,5W	-	Cri,Idc	BZX55/..,BZX83/..,ZPD..,1N5221..61,+
1N3393	Z-Di	=1N3392:1,8V	-		-
1N3394	Z-Di	=1N3392:2,2V	-		-
1N3395	Z-Di	=1N3392:2,7V	-		-
1N3396	Z-Di	=1N3392:3,3V	-		-
1N3397	Z-Di	=1N3392:3,9V	-		-
1N3398	Z-Di	=1N3392:4,7V	-		-
1N3399	Z-Di	=1N3392:5,6V	-		-
1N34(A)	Ge-Di	Uni,Dem,75V,50mA	31a	EUR,USA,Nec	AA113,1N60
1N340	Si-Di	=2N338:0,6A	32a$	USA	BYX38/300,BYX39/600
1N3400	Z-Di	=1N3392:6,8V	-		-
1N3401	Z-Di	=1N3392:8,2V	-		-
1N3402	Z-Di	=1N3392:10V	-		-

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1N3403	Z-Di	=1N3392:12V	-		-
1N3404	Z-Di	=1N3392:15V	-		-
1N3405	Z-Di	=1N3392:18V	-		-
1N3406	Z-Di	=1N3392:22V	-		-
1N3407	Z-Di	=1N3392:27V	-		-
1N3408	Z-Di	=1N3392:33V	-		-
1N3409	Z-Di	=1N3392:39V	-		-
1N341	Si-Di	=2N338:400V,1,2A	32a$	USA	BYX38/600,BYX39/600
1N3410	Z-Di	=1N3392:47V	-		-
1N3411	Z-Di	6,2V,10%,0,5W	-	Cri,Idc	BZX55/..,BZX83/..,ZPD..,1N5234..81,+
1N3412	Z-Di	=1N3411:6,8V	-		-
1N3413	Z-Di	=1N3411:7,5V	-		-
1N3414	Z-Di	=1N3411:8,2V	-		-
1N3415	Z-Di	=1N3411:10V	-		-
1N3416	Z-Di	=1N3411:12V	-		-
1N3417	Z-Di	=1N3411:15V	-		-
1N3418	Z-Di	=1N3411:18V	-		-
1N3419	Z-Di	=1N3411:22V	-		-
1N342	Si-Di	=2N338:400V,0,6A	32a$	USA	BYX38/600,BYX39/600
1N3420	Z-Di	=1N3411:27V	-		-
1N3421	Z-Di	=1N3411:30V	-		-
1N3422	Z-Di	=1N3411:33V	-		-
1N3423	Z-Di	=1N3411:39V	-		-
1N3424	Z-Di	=1N3411:47V	-		-
1N3425	Z-Di	=1N3411:56V	-		-
1N3426	Z-Di	=1N3411:68V	-		-
1N3427	Z-Di	=1N3411:82V	-		-
1N3428	Z-Di	=1N3411:100V	-		-
1N3429	Z-Di	=1N3411:120V	-		-
1N343	Si-Di	=2N338:300V,1,2A	32a$	USA	BYX38/600,BYX39/600
1N3430	Z-Di	=1N3411:150V	-		-
1N3431	Z-Di	=1N3411:180V	-		-
1N3432	Z-Di	=1N3411:220V	-		-
1N3433	Z-Di	8,2V,2W	-		BZD23/..,BZV47/..,BZX70/..
1N3434	Z-Di	=1N3433:10V	-		-
1N3435	Z-Di	=1N3433:12V	-		-
1N3436	Z-Di	=1N3433:15V	-		-
1N3437	Z-Di	=1N3433:18V	-		-
1N3438	Z-Di	=1N3433:22V	-		-
1N3439	Z-Di	=1N3433:27V	-		-
1N344	Si-Di	GI-L,300V,0,6A	32a$	USA	BYX38/300,BYX39/600
1N3440	Z-Di	=1N3433:33V	-		-
1N3441	Z-Di	=1N3433:39V	-		-
1N3442	Z-Di	=1N3433:47V	-		-
1N3443	Z-Di	6,2V,10%,2W	-		BZD23/..,BZV47/..,BZX70/..
1N3444	Z-Di	=1N3443:6,8V	-		-
1N3445	Z-Di	=1N3443:8,2V	-		-
1N3446	Z-Di	=1N3443:10V	-		-
1N3447	Z-Di	=1N3443:12V	-		-
1N3448	Z-Di	=1N3443:15V	-		-
1N3449	Z-Di	=1N3443:18V	-		-
1N345	Si-Di	=1N344:200V,1,2A	32a$	USA	BYX38/300,BYX39/600
1N3450	Z-Di	=1N3443:22V	-		-
1N3451	Z-Di	=1N3443:27V	-		-
1N3452	Z-Di	=1N3443:30V	-		-
1N3453	Z-Di	=1N3443:33V	-		-
1N3454	Z-Di	=1N3443:39V	-		-
1N3455	Z-Di	=1N3443:47V	-		-
1N3456	Z-Di	=1N3443:56V	-		-
1N3457	Z-Di	=1N3443:68V	-		-
1N3458	Z-Di	=1N3443:82V	-		-
1N3459	Z-Di	=1N3443:100V	-		-
1N346	Si-Di	=1N344:200V,0,6A	32a$	USA	BYX38/300,BYX39/600
1N3460	Z-Di	=1N3443:120V	-		-

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1N3461	Z-Di	=1N3443:150V	-		-
1N3462	Z-Di	=1N3443:180V	-		-
1N3463	Z-Di	=1N3443:220V	-		-
1N3464	Si-Di	kV-Gl,12kV,0,06A	31a	Gen,Sol	1N3052
1N3465	Ge-Di	Uni,60V,75mA	31a	USA,Itt	AA117..118,AA132..134,1N34,1N54,+
1N3466	Ge-Di	Uni,40V,75mA	31a	USA,Itt	AA117..118,AA132..134,1N34,1N54,+
1N3467	Ge-Di	SS,18V,<2ns	31a	USA,Itt	-
1N3468	Ge-Di	SS,18V,<2ns	31a	USA,Itt	-
1N3469	Ge-Di	Uni,35V,85mA	31a	USA,Itt	AA135..136,1N634..635
1N347	Si-Di	=1N344:100V,3A	32a$	USA	BYX38/300,BYX39/600
1N3470	Ge-Di	Uni,35V,85mA	31a	USA	AA135..136,1N634..635
1N3471	Si-Di	SS,40V,0,04A,<3pF,<2ns	-	Idc,Wes	BA218;BAX13,BAX91,1N4148..49,+
1N3473	Si-Di	Gl,200V	-		-
1N3474	Si-Di	=1N3473:400V	-		-
1N3475	Si-Di	=1N3473:600V	-		-
1N3476	Si-Di	=1N3473:800V	-		-
1N3477	Z-Di	2,2V,10%,0,25W	31a	Idc,Gie	BZX55/C2V4,BZX79/C2V4,1N5221
1N3477A	Z-Di	=1N3477:5%	31a	-	-
1N3478	Si-Di	Gl,Uni,200V	-		BY126..127,BY133..134,1N4003..07,+
1N3479	Si-Di	=1N3478:400V	-		BY126..127,BY133..134,1N4004..07,+
1N348	Si-Di	=1N344:100V,1,2A	32a$	USA	BYX38/300,BYX39/600
1N3480	Si-Di	=1N3478:600V	-		BY126..127,BY133..134,1N4005..07,+
1N3481	Ge-Di	UHF,X-Band-S,9GHz	Koax	Phc	-
1N3482	Ge-Di	UHF,X-Band-S,9GHz	Koax	Phc	-
1N3483	Ge-Di	Uni,8V	31a	USA	-
1N3484	Ge-Di	Uni,75V,<4pF(0,75V)	31a	Idc,Sem	AA117..118,AA132..133
1N3485	Si-Di	S,175V,<50ns	31a	Cri	BA197..198,BAV20..21,1N3070,+
1N3486	Si-Di	Gl,1000V,0,4A	34a	USA	BA159,BY127,BY133,BY204/10,+
1N3487	Si-Di	=1N3486:1200V	34a	-	BY127,BY133,BYX94..95,GP10Q,+
1N3488	Si-Di	VHF-Tuning,15V,56pF(4V)	31a	Gie,Trw	-
1N3489(A)	Trigger-Di	Ub=16..24V,Ib<0,125mA,Itsm=10A	31a	Mdc,Spe	-
1N349	Si-Di	=1N344:100V,0,6A	32a$	USA	BYX38/300,BYX39/600
1N3490	Trigger-Di	=1N3489	31a	-	-
1N3491	Si-Di	Gl-L,50V,25A(Tc=130o)	75a$	USA,Mot	SSiE1205..1240,1N3659..3665
1N3491R...3495R	Si-Di	=1N3491..3495:	75b&	-	DS25-..A,SSiE1105..40,1N3659R..65R
1N3491R..3495R	Si-Di	-	75b&	-	DS25-..A,SSiE1105..40,1N3659R..65R
1N3492	Si-Di	=1N3491:100V	75a$	-	SSiE1210..1240,1N3660..3665
1N3493	Si-Di	=1N3491:200V	75a$	-	SSiE1220..1240,1N3661..3665
1N3494	Si-Di	=1N3491:300V	75a$	-	SSiE1220..1240,1N3662..3665
1N3495	Si-Di	=1N3491:400V	75a$	-	SSiE1230..1240,1N3663..3665
1N3496	Ref-Di	6,2V,5%,0,25W	31a	USA,Sie,Tho	BZV11,BZV28,BZX91,1N4581
1N3497	Ref-Di	6,2V,5%,0,25W	31a	-	BZV12,BZV29,BZX92,1N4582
1N3498	Ref-Di	6,2V,5%,0,25W	31a	-	BZV13,BZV30,BZX93,1N4583
1N3499	Ref-Di	6,2V,5%,0,25W	31a	-	BZV14,BZV31,BZX94,1N4584
1N35	Ge-Di	FM-Dem,gep,75V,22,5mA	2x31a	USA,Nec,Tho	AA113,1N34
1N350	Si-Di	Uni,70V,15mA	2c	USA	BA147/100,BAY19..21,BAY45..46,+
1N3500	Ref-Di	6,2V,5%,0,25W	31a	-	BZV10,BZV27,BZX90,1N4580
1N3501	Ref-Di	6,35V,2%,0,25W	31a	USA,Sie	1N4890
1N3502	Ref-Di	6,35V,2%,0,25W	31a	-	1N4891
1N3503(A)	Ref-Di	6,35V,2%,0,25W	31a	-	1N4890..95
1N3504(A)	Ref-Di	6,35V,2%,0,25W	31a	-	1N4890..95
1N3506	Z-Di	3,3V,5%,0,4W	31a	USA,Sie,Tix	BZX55/..,BZX83/..,ZPD..,1N5226..61,..
1N3507	Z-Di	=1N3506:3,6V	31a	-	-
1N3508	Z-Di	=1N3506:3,9V	31a	-	-
1N3509	Z-Di	=1N3506:4,3V	31a	-	-
1N351	Si-Di	=1N350:120V	2c	USA	BA147/150,BAY20..21,BAY45..46,+
1N3510	Z-Di	=1N3506:4,7V	31a	-	-
1N3511	Z-Di	=1N3506:5,1V	31a	-	-
1N3512	Z-Di	=1N3506:5,6V	31a	-	-
1N3513	Z-Di	=1N3506:6,2V	31a	-	-
1N3514	Z-Di	=1N3506:6,8V	31a	-	-
1N3515	Z-Di	=1N3506:7,5V	31a	-	-
1N3516	Z-Di	=1N3506:8,2V	31a	-	-
1N3517	Z-Di	=1N3506:9,1V	31a	-	-

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1N3518	Z-Di	=1N3506:10V	31a	-	-
1N3519	Z-Di	=1N3506:11V	31a	-	-
1N352	Si-Di	=1N350:170V	2c	USA	BA147/230,BAY20..21,BAY46,+
1N3520	Z-Di	=1N3506:12V	31a	-	-
1N3521	Z-Di	=1N3506:13V	31a	-	-
1N3522	Z-Di	=1N3506:15V	31a	-	-
1N3523	Z-Di	=1N3506:16V	31a	-	-
1N3524	Z-Di	=1N3506:18V	31a	-	-
1N3525	Z-Di	=1N3506:20V	31a	-	-
1N3526	Z-Di	=1N3506:22V	31a	-	-
1N3527	Z-Di	=1N3506:24V	31a	-	-
1N3528	Z-Di	=1N3506:27V	31a	-	-
1N3529	Z-Di	=1N3506:30V	31a	-	-
1N353	Si-Di	=1N350:225V	2c	USA	BA147/300,BAY21,BAY46,BAY88,+
1N3530	Z-Di	=1N3506:33V	31a	-	-
1N3531	Z-Di	=1N3506:36V	31a	-	-
1N3532	Z-Di	=1N3506:39V	31a	-	-
1N3533	Z-Di	=1N3506:43V	31a	-	-
1N3534	Z-Di	=1N3506:47V	31a	-	-
1N3535	Si-Di	200V	-		-
1N3536	Si-Di	70V	-		-
1N3537	Z-Di	12V,10%,1W	34a	USA	BZW22/C12,BZX61/C12,ZPY12,1N5927,+
1N3538	Si-Di	150V	-		-
1N3539(A)	Si-Di	Backward-Di,1mA,Uf>0,6V(47?A),<10pF	2	Msc	-
1N354	Si-Di	=1N350:325V	2c	USA	BA147/300,BAY21,BAY46,BAY88,+
1N3540(A)	Si-Di	Backward-Di,2mA,Uf>0,6V(0,1mA),<20pF	2	Msc	-
1N3541(A)	Si-Di	Backward-Di,2,5m,Uf>0,6V(0,22mA)	2	Msc	-
1N3542(A)	Si-Di	Backward-Di,3mA,Uf>0,6V(0,47mA)	2	Msc	-
1N3543(A)	Si-Di	Backward-Di,5mA,Uf>0,6V(1mA),<100pF	2	Msc	-
1N3544	Si-Di	Gl,Uni,100V,0,6A	31a	USA	BY126..127,BY133..134,1N4002..07,+
1N3545	Si-Di	=1N3544:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N3546	Si-Di	=1N3544:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3547	Si-Di	=1N3544:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3548	Si-Di	=1N3544:500V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3549	Si-Di	=1N3544:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N355	Ge-Di	Uni,80V,50mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N3550	Si-Di	S,180V,0,08A,<1,5?s	31a	USA	BA157..159,BA199/250,BAY46,+
1N3551	Si-Di	VHF-Tuning,11V,50pF(4V)	31a	Trw	-
1N3552(A)	Si-Di	VHF-Tuning,22V,21pF(4V)	31a	Trw	-
1N3553	Ref-Di	0,25V,0,25W	31a	USA	-
1N3554	Si-Di	VHF-Tuning,100V,12pF(4V)	31a	Trw	-
1N3555	Si-Di	VHF-Tuning,100V,20pF(4pF)	31a	Trw	-
1N3556	Si-Di	VHF-Tuning,100V,47pF(4V)	31a	Trw	-
1N3557	Si-Di	VHF-Tuning,210V,24pF(8V)	31a	Trw	-
1N3558	Si-Di	=2x1N751gep	-		→1N751
1N3559	Ge-Di	Uni,24V,Ifsm=0,5A,20pF	31a	Idc,Sem	AA139,1N270
1N3560	Ge-Di	Tunnel-Di,<20pF,Up=55mV,Uv=320mV	2	Phc	-
1N3561	Ge-Di	Tunnel-Di,<20pF,Up=55mV,Uv=320mV	2	Phc	-
1N3562	Ge-Di	Tunnel-Di,<85pF,Up=55mV,Uv=320mV	2	Phc	-
1N3563	Si-Di	Gl,1000V,0,4A	34a	USA,Rca	BA159,BY127,BY133,1N4007,+
1N3564	Ge-Di	Uni,gep,15V	31a	Idc,Sem	AA112..113,AA116,1N34,1N54,1N60,+
1N3565	Si-Di	6V,2A	32	USA	-
1N3566	Si-Di	Gl-L,800V,1A	32a	Cri	BYX38/900,BYX39/800
1N3567	Si-Di	Min,75V,0,06A,<2pF(0V),<2ns	31a	USA	(BA218,BAX13,BAX91,1N4148..49,++)
1N3568	Si-Di	Min,80V,<2pF(0V),<4ns	31a	USA	(BA218,BAX13,BAX91,1N4148..49,++)
1N3569	Si-Di	Gl-L,100V,3,5A(Tc=85o)	32a$	USA,Gen,Mot	BYX38/300,BYX39/600
1N3570	Si-Di	=1N3569:200V	32a$	-	BYX38/300,BYX39/600
1N3571	Si-Di	=1N3569:300V	32a$	-	BYX38/300,BYX39/600
1N3572	Si-Di	=1N3569:400V	32a$	-	BYX38/600,BYX39/600
1N3573	Si-Di	=1N3569:500V	32a$	-	BYX38/600,BYX39/600
1N3574	Si-Di	=1N3569:600V	32a$	-	BYX38/600,BYX39/600
1N3575	Si-Di	Gl,60V,0,15A	34a	USA	BA147/100,BA157..159,BAY19,+
1N3576	Si-Di	=1N3575:125V	34a	-	BA147/150,BA157..159,BAY20,+
1N3577	Si-Di	=1N3575:175V	34a	-	BA147/230,BA157..159,BAY20,+

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1N3578	Si-Di	=1N3575:225V	34a	-	BA147/230,BA157..159,BAY21,+
1N3579	Si-Di	=1N3575:275V	34a	-	BA147/300,BA157..159,BAY21,+
1N358(A)	Si-Di	UHF,L/X-Band-Dem,6750MHz	Koax	USA	-
1N3580(A,B)	Ref-Di	11,7V,5%,0,75W	34a	USA,Mot	1N941
1N3581(A,B)	Ref-Di	11,7V,5%,0,75W	34a	-	1N942
1N3582(A,B)	Ref-Di	11,7V,5%,0,75W	34a	-	1N943
1N3583(A,B)	Ref-Di	11,7V,5%,0,75W	34a	-	1N944
1N3584(A,B)	Ref-Di	11,7V,5%,0,75W	34a	-	1N945
1N3585	Si-Di	Gl-L,50V,400A(Tc=120o)	73a$	Cri,Ssi	-
1N3586	Si-Di	=1N3585:100V	73a$	-	-
1N3587	Si-Di	=1N3585:200V	73a$	-	-
1N3588	Si-Di	=1N3585:300V	73a$	-	-
1N3589	Si-Di	=1N3585:400V	73a$	-	-
1N359(A)	Si-Di	Gl,50V,0,15A	34a	USA	BA147/50,BAY18..21,1N4001..07,+
1N3590	Si-Di	=1N3585:500V	73a$	-	-
1N3591	Si-Di	=1N3585:600V	73a$	-	-
1N3592	Ge-Di	S,30V,0,05A,<1pF(0V),<70ns	31a	USA,Tho	AAY27
1N3593	Si-Di	Min,S,40V,0,05A,<4pF(0V),10ns	31a	Idc,Sem	(BA218,BAX13,BAX91,1N4148..49,++)
1N3594	Si-Di	Min,S,60V,<4pF(0V),6ns	31a	Idc,Msc,Sem	(BA218,BAX13,BAX91,1N4148..49,++)
1N3595	Si-Di	S,150V,0,1A,<8pF(0V),<3?s	31a	USA,Tho	BA147/150,BA157..159,1N5606..07,+
1N3596	Si-Di	SS,20V,0,075A,<1pF(0V),<4ns	31a	USA	BA217,BA317,BAY71,1N4148..49,+
1N3597	Si-Di	S,200V,0,275A,<5pF(0V),<300ns	31a	USA	BA157..159,BA173,BY206..207,+
1N3598	Si-Di	SS,50V,0,075A,<2pF(0V),<4ns	31a	USA	BA218,BAX13,BAX91,1N4148..49,+
1N3599	Si-Di	S,150V,<10pF(0V),<50ns	31a	USA	BA196..198,BAV20..21,BAY80,+
1N36	Ge-Di	HF-Dem,36V,16mA	31a	Kem,Sem,Tho	AA113,AA119,1N34,1N60
1N360(A)	Si-Di	=1N359:100V	34a	USA	BA147/100,BAY19..21,1N4002..07,+
1N3600	Si-Di	SS,50V,0,2A,<2,5pF(0V),<4ns	31a	USA,Tho	BAW62,BAX95,BAY95,1N4148..49,+
1N3601	Si-Di	SS,75V,<3pF(0V),<5ns	31a	USA	BAW62,BAX95,BAW76,1N4148..49,+
1N3602	Si-Di	SS,75V,0,115A,<3pF(0V),<5ns	31a	USA	BAW62,BAX95,BAW76,1N4148..49,+
1N3603	Si-Di	=1N3602:45V	31a	-	BAW62,BAX95,BAW76,1N4148..49,+
1N3604	Si-Di	=1N4151	31a	USA,Sie,Tho	→1N4151
1N3605	Si-Di	=1N4152	31a	-	→1N4152
1N3606	Si-Di	=1N4153	31a	-	→1N4153
1N3607	Si-Di	=1N4151:Min	31a	-	→1N4151
1N3608	Si-Di	=1N4152:Min	31a	-	→1N4152
1N3609	Si-Di	=1N4153:Min	31a	-	→1N4153
1N361(A)	Si-Di	=1N359:200V	34a	USA	BA147/230,BAY21,1N4003..07,+
1N3611(GP)	Si-Di	Gl,200V,1A	31a	USA,Sie	BY126..127,BY133..134,1N4003..07,+
1N3612(GP)	Si-Di	=1N3611:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3613(GP)	Si-Di	=1N3611:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3614(GP)	Si-Di	=1N3611:800V	31a	-	BY127,BY133,1N4006..07,+
1N3615	Si-Di	Gl-L,50V,16A(Tc=150o)	32a$	USA,Mot	BYX25/600,BYX99/600
1N3616	Si-Di	=1N3615:100V	32a$	-	BYX25/600,BYX99/600
1N3617	Si-Di	=1N3615:150V	32a$	-	BYX25/600,BYX99/600
1N3618	Si-Di	=1N3615:200V	32a$	-	BYX25/600,BYX99/600
1N3619	Si-Di	=1N3615:300V	32a$	-	BYX25/600,BYX99/600
1N362(A)	Si-Di	=1N359:350V	34a	USA	BAY21,BAY88..90,1N4003..07,+
1N3620	Si-Di	=1N3615:400V	32a$	-	BYX25/600,BYX99/600
1N3621	Si-Di	=1N3615:500V	32a$	-	BYX25/600,BYX99/600
1N3622	Si-Di	=1N3615:600V	32a$	-	BYX25/600,BYX99/600
1N3623	Si-Di	=1N3615:800V	32a$	-	BYX25/800,BYX99/900
1N3624	Si-Di	=1N3615:1000V	32a$	-	BYX25/1000,BYX99/1200
1N3625	Si-Di	S,200V,0,15A	31a	USA	BA157..159,BY204/4,BY206..207,+
1N3626	Ge-Di	Uni,50V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N3627	Si-Di	VHF-Tuning,20V,21pF(4V)	31a	Gie,Tdy	-
1N3628	Si-Di	VHF-Tuning,20V,50pF(4V)	31a	Gie,Tdy	-
1N3629	Si-Di	Gl,100V,0,75A	31a	Cri,Ssi	BY126..127,BY133..135,1N4002..07,+
1N363(A)	Si-Di	=1N359:500V	34a	USA	BA158..159,BAY89..90,1N4005..07,+
1N3630	Si-Di	=1N3629:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N3631	Si-Di	=1N3629:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3632	Si-Di	=1N3629:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3633	Si-Di	=1N3629:500V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3634	Si-Di	=1N3629:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3635	Si-Di	=1N3629:700V	31a	-	BY127,BY133,BY227,1N4006..07,+

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1N3636	Si-Di	=1N3629:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N3637	Si-Di	=1N3629:900V	31a	-	BY127,BY133,BY227,1N4007,+
1N3638	Si-Di	=1N3629:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N3639	Si-Di	GI,200V,0,75A	34a	USA	BY126..127,BY133..134,1N4003..07,+
1N364(A)	Si-Di	=1N359:850V	34a	USA	BA159,BAY90..91,1N4007
1N3640	Si-Di	=1N3639:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N3641	Si-Di	=1N3639:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N3642	Si-Di	=1N3639:800V	34a	-	BY127,BY133,BY227,1N4006..07,+
1N3643	Si-Di	GI,1000V,0,25A	31a	USA	BA159,BY127,BY133,1N4007,+
1N3644	Si-Di	=1N3643:1500V	31a	-	BAY91,BY203/16,BY269,GP10W,+
1N3645	Si-Di	=1N3643:2000V	31a	-	BAY91,BY203/20,GP02-20,MR250-2,+
1N3646	Si-Di	=1N3643:2500V	31a	-	GP02-30,MR250-3,1N1733A
1N3647	Si-Di	=1N3643:3000V	31a	-	GP02-30,MR250-3,1N1733A
1N3648	Si-Di	kV-GI,10kV,0,35A	31a	Cri	-
1N3649	Si-Di	GI-L,800V,3,3A(Tc=50o)	32a$	USA,Mot,Tix	BYX38/900,BYX39/800
1N3649R...3650R	Si-Di	=1N3649..3650:	32b&	-	BYX38/..R,BYX39/..R
1N3649R..3650R..	Si-Di	-	32b&	-	BYX38/..R,BYX39/..R
1N365(A)	Si-Di	=1N359:1000V	34a	USA	BA159,BAY90..91,1N4007
1N3650	Si-Di	=1N3649:1000V	32a$	-	BYX38/1200,BYX39/1000
1N3653	Si-Di	SS,100V,<4ns	31a	USA	(BAV14)
1N3654	Si-Di	SS,100V,<4ns	31a	USA	BA219,BAX96
1N3655(A,B)	Si-Di	UHF,S-Band-M,3060MHz	-	USA	-
1N3656	Si-Di	GI,Uni,200V,0,75A	31a	USA	BY126..127,BY133..134,1N4003..07,+
1N3657	Si-Di	=1N3656:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3658	Si-Di	=1N3656:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3659	Si-Di	GI-L,50V,30A(Tc=100o)	75a$	USA,Mot	SSiE1105..1140
1N3659R...3665R	Si-Di	=1N3659..3665:	75b&	-	SSiE1205..1240
1N3659R..3665R..	Si-Di	-	75b&	-	SSiE1205..1240
1N3660	Si-Di	=1N3659:100V	75a$	-	SSiE1110..1140
1N3661	Si-Di	=1N3659:200V	75a$	-	SSiE1120..1140
1N3662	Si-Di	=1N3659:300V	75a$	-	SSiE1120..1140
1N3663	Si-Di	=1N3659:400V	75a$	-	SSiE1130..1140
1N3664	Si-Di	=1N3659:500V	75a$	-	SSiE1130..1140
1N3665	Si-Di	=1N3659:600V	75a$	-	SSiE1140
1N3666	Ge-Di	Uni,S,80V,0,07A,<1pF(0V),<300ns	31a	USA	AAY28,AAZ15,1N633
1N3667	Si-Di	GI-L,500V,1,5A(Tc=120o)	-	Cri	-
1N3668	Si-Di	S,30V,0,075A,<1pF(0V),<150ns	31a	USA	BAX85,BAX89..90,BAX94,1N4148..49+
1N3669	Si-Di	S,70V,0,4A,<10pF(0V),<200ns	31a	USA	BA157..159,BAV15..16,BAX12,+
1N367	Ge-Di	Uni,60V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N3670(A)	Si-Di	GI-L,700V,12A(Tc=150o)	32a$	USA,Mot	BYW88/800,BYX80..81,1N4509..11
1N3670R...3673R	Si-Di	=1N3670..3673:	32b&	-	BYW88/..R,BYX80R..81R
1N3670R..3673R..	Si-Di	-	32b&	-	BYW88/..R,BYX80R..81R
1N3671(A)	Si-Di	=1N3670:800V	32a$	-	BYW88/800,BYX80..81,1N4509..11
1N3672(A)	Si-Di	=1N3670:900V	32a$	-	BYW88/1000,BYX81,1N4510..11
1N3673(A)	Si-Di	=1N3670:1000V	32a$	-	BYW88/1000,BYX81,1N4510..11
1N3675	Z-Di	6,8V,20%,0,75W	31a	USA,Mot	BZV85/..,BZW22/..,ZPY..,1N3016..51,+
1N3675A...3710A	Z-Di	=1N3675..3710:10%	31a	-	-
1N3675A..3710A..	Z-Di	=1N3675..3710:10%	31a	-	-
1N3675B...3710B	Z-Di	=1N3675..3710:5%	31a	-	-
1N3675B..3710B..	Z-Di	=1N3675..3710:5%	31a	-	-
1N3676	Z-Di	=1N3675:7,5V	31a	-	-
1N3677	Z-Di	=1N3675:8,2V	31a	-	-
1N3678	Z-Di	=1N3675:9,1V	31a	-	-
1N3679	Z-Di	=1N3675:10V	31a	-	-
1N368(A)	Ge-Di	GI,200V,0,1A	34a	USA	-
1N3680	Z-Di	=1N3675:11V	31a	-	-
1N3681	Z-Di	=1N3675:12V	31a	-	-
1N3682	Z-Di	=1N3675:13V	31a	-	-
1N3683	Z-Di	=1N3675:15V	31a	-	-
1N3684	Z-Di	=1N3675:16V	31a	-	-
1N3685	Z-Di	=1N3675:18V	31a	-	-
1N3686	Z-Di	=1N3675:20V	31a	-	-
1N3687	Z-Di	=1N3675:22V	31a	-	-
1N3688	Z-Di	=1N3675:24V	31a	-	-

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1N3689	Z-Di	=1N3675:27V	31a	-	-
1N369(A)	Si-Di	UHF,S/X-(A:L/X-)Band-Dem,6750MHz	Koax	USA	-
1N3690	Z-Di	=1N3675:30V	31a	-	-
1N3691	Z-Di	=1N3675:33V	31a	-	-
1N3692	Z-Di	=1N3675:36V	31a	-	-
1N3693	Z-Di	=1N3675:39V	31a	-	-
1N3694	Z-Di	=1N3675:43V	31a	-	-
1N3695	Z-Di	=1N3675:47V	31a	-	-
1N3696	Z-Di	=1N3675:51V	31a	-	-
1N3697	Z-Di	=1N3675:56V	31a	-	-
1N3698	Z-Di	=1N3675:62V	31a	-	-
1N3699	Z-Di	=1N3675:68V	31a	-	-
1N370	Z-Di	1,85V,20%,0,2W	31a	USA	BZX55/..,BZX79/..,ZPD..,1N5221..36,+
1N3700	Z-Di	=1N3675:75V	31a	-	-
1N3701	Z-Di	=1N3675:82V	31a	-	-
1N3702	Z-Di	=1N3675:91V	31a	-	-
1N3703	Z-Di	=1N3675:100V	31a	-	-
1N3704	Z-Di	=1N3675:110V	31a	-	-
1N3705	Z-Di	=1N3675:120V	31a	-	-
1N3706	Z-Di	=1N3675:130V	31a	-	-
1N3707	Z-Di	=1N3675:150V	31a	-	-
1N3708	Z-Di	=1N3675:160V	31a	-	-
1N3709	Z-Di	=1N3675:180V	31a	-	-
1N371	Z-Di	=1N370:2,35V,15%	31a	-	-
1N3710	Z-Di	=1N3675:200V	31a	-	-
1N3711	Si-Di	kV-Gl,6kV,0,15A	31a	Cri,Sem	BYX90
1N3712	Ge-Di	Tunnel-Di,Ip=1mA,Iv=0,12mA,3,2GHz	34a	Gen	-
1N3713	Ge-Di	Tunnel-Di,Ip=1mA,Iv=95?A,3,2GHz	34a	Gen	-
1N3714	Ge-Di	Tunnel-Di,Ip=2,2mA,Iv=290?A,2,2GHz	34a	Gen	-
1N3715	Ge-Di	Tunnel-Di,Ip=2,2mA,Iv=210?A,3GHz	34a	Gen	-
1N3716	Ge-Di	Tunnel-Di,Ip=4,7mA,Iv=0,6mA,1,7GHz	34a	Gen	-
1N3717	Ge-Di	Tunnel-Di,Ip=4,7mA,Iv=0,45mA,3,4GHz	34a	Gen	-
1N3718	Ge-Di	Tunnel-Di,Ip=10mA,Iv=1,3mA,1,6GHz	34a	Gen	-
1N3719	Ge-Di	Tunnel-Di,Ip=10mA,Iv=950?A,2,8GHz	34a	Gen	-
1N372	Z-Di	=1N370:2,9V,15%	31a	-	-
1N3720	Ge-Di	Tunnel-Di,Ip=22mA,Iv=2,9mA,1,6GHz	34a	Gen	-
1N3721	Ge-Di	Tunnel-Di,Ip=22mA,Iv=2,1mA,2,6GHz	34a	Gen	-
1N3722	Si-Di	Min,S,50V,<4pF(0V),<10ns	31a	USA	(BA218,BAX13,BAX91,1N4148..49,++)
1N3723	Si-Di	Gl,1000V,0,75A	31a	Sem,Sol	BY127,BY133,BY227,1N4007,+
1N3724	Si-Di	=1N3723:1200V	31a	-	BY127,BY133,BY227,GP10Q,+
1N3725	Si-Di	=1N3723:1400V	31a	-	BY400,BY448,EM516,GP10W,+
1N3726	Si-Di	=1N3723:1600V	31a	-	BY400,DM513,EM516,GP10Y
1N3727	Si-Di	=1N3723:1800V	31a	-	DM516
1N3728	Si-Di	Gl,Uni,550V,0,2A	31a	Sem,Ssi	BA158..159,BA199/550,BAY89..90,+
1N3729	Si-Di	Gl,S,600V,<3pF(0V),<500ns	31a	Sem,Ssi	BY208/600,BY295/600,BY407,+
1N373	Z-Di	=1N370:3,5V,15%	31a	-	-
1N3730	Si-Di	S,80V,<12pF(0V),<15ns	31a	USA	BAW26..27
1N3731	Si-Di	SS,100V,0,175A,<2pF(0V),<3ns	31a	USA	-
1N3732	Z-Di	5,1V,5%,1W	34a	USA	BZW22/C5V1,BZX61/C5V1,ZPY5,1,1N5918+
1N3733	Si-Di	UHF,S-Band-M,3060MHz	Koax	Miv	-
1N3734	Opto	-		-	-
1N3735	Si-Di	Gl-L,100V,250A(Tc=130o)	73a$	USA,Tho	-
1N373SR...3744R	Si-Di	=1N3735..3744:	73b&	-	DS40-..A
1N373SR..3744R	Si-Di	-	73b&	-	DS40-..A
1N3736	Si-Di	=1N3735:200V	73a$	-	-
1N3737	Si-Di	=1N3735:300V	73a$	-	-
1N3738	Si-Di	=1N3735:400V	73a$	-	-
1N3739	Si-Di	=1N3735:500V	73a$	-	-
1N374	Z-Di	=1N370:4,1V,10%	31a	-	-
1N3740	Si-Di	=1N3735:600V	73a$	-	-
1N3741	Si-Di	=1N3735:800V	73a$	-	-
1N3742	Si-Di	=1N3735:1000V	73a$	-	-
1N3743	Si-Di	=1N3735:1200V	73a$	-	-
1N3744	Si-Di	=1N3735:1400V	73a$	-	-

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1N3745	Si-Di	UHF,X-Band-M,9375MHz	Koax	USA	-
1N3746	Si-Di	UHF,X-Band-M,9375MHz	Koax	USA	-
1N3747	Si-Di	UHF,X-Band-M,9375MHz	Koax	USA	-
1N3748	Si-Di	Gl,200V,0,5A	31a	Edl,Sem	BY126..127,BY133..134,1N4003..07,+
1N3749	Si-Di	=1N3748:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N375	Z-Di	=1N370:4,1V,5%	31a	-	-
1N3750	Si-Di	=1N3748:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3751	Si-Di	=1N3748:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N3752	Si-Di	=1N3748:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N3753	Ge-Di	Uni,55V	31a	Idc,Sem	AA117..118,AA132..134,1N34,1N54,+
1N3754	Si-Di	Gl,100V,0,125A	2c	Rca,Sem,Tos	BA157..159,BY204/4,BY206..207,+
1N3755	Si-Di	=1N3754:200V	2c	-	BA157..159,BY204/4,BY206..207,+
1N3756	Si-Di	=1N3754:400V	2c	-	BA157..159,BY204/4,BY206..207,+
1N3757	Si-Di	Gl,200V,1A	31a	USA	BY126..127,BY133..134,1N4003..07,+
1N3758	Si-Di	=1N3757:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3759	Si-Di	=1N3757:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N376	Z-Di	=1N370:4,95V,5%	31a	-	-
1N3760	Si-Di	=1N3757:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N3761	Si-Di	=1N3757:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N3762	Si-Di	kV-Gl,7,5kV,0,065A	31a	Sem	BYX90,1N5183
1N3763	Ref-Di	20V,5%,1,5W	31a	Idc,Msc,Sie	-
1N3764	Si-Di	kV-Gl,3kV,0,4A	31a	USA	1N1733A
1N3765	Si-Di	Gl-L,700V,35A(Tc=140o)	32a$	USA,Mot,Tho	1N4528
1N3765R...3768R	Si-Di	=1N3765..3768:	32b&	-	D34C/...C
1N3765R..3768R	Si-Di	-	32b&	-	D34C/..C
1N3765T...3768T	Si-Di	=1N3765..3768:	73a$	-	-
1N3765T..3768T	Si-Di	-	73a$	-	-
1N3766	Si-Di	=1N3765:800V	32a$	-	1N4528
1N3767	Si-Di	=1N3765:900V	32a$	-	1N4529
1N3768	Si-Di	=1N3765:1000V	32a$	-	1N4529
1N3769	Ge-Di	Uni,90V	31a	USA	AA117..118,AA132..133
1N377	Z-Di	=1N370:5,9V,5%	31a	-	-
1N3770	Si-Di	UHF-Tuning,5,5V,<2pF(0V),140GHz	-	Miv	-
1N3771	Trigger-Di	Ub>170V	31a	Mdc,Spe	-
1N3772	Trigger-Di	Ub=15..25V,Ib<0,4mA,Itsm=10A	31a	Mdc,Spe	-
1N3773	Ge-Di	S,25V,<1,2pF(0V),<40ns	31a	USA	-
1N3774	Ref-Di	1,15V,2%,0,34W	31a	Idc,Sem	-
1N3775	Si-Di	Gl-L,1500V,3,3A(Tc=50o)	32a$	USA	-
1N3776	Z-Di	10V,10%,6W	32	Cri	BZX98/C10,BZY93/C10,ZL10,1N2974,+
1N3777	Si-Di	Gl-L,800V,35A(Tc=140o)	32a$	USA	1N3766..68,1N4528..30
1N3778	Si-Di	UHF,C/X-Band-Dem,9375MHz	Koax	Mic,Pai	-
1N3779	Ref-Di	6,5V,3%,0,4W	31a	Inr,Sie,++	BZV10,BZV27,BZX90,1N4580
1N378	Z-Di	=1N370:7,15V,5%	31a	-	-
1N3780	Ref-Di	6,5V,3%,0,4W	31a	-	BZV10,BZV27,BZX90,1N4580
1N3781	Ref-Di	6,5V,3%,0,4W	31a	-	BZV11,BZV28,BZX91,1N4581
1N3782	Ref-Di	6,5V,3%,0,4W	31a	-	BZV12,BZV29,BZX92,1N4582
1N3783	Ref-Di	6,5V,3%,0,4W	31a	-	BZV13,BZV30,BZX93,1N4583
1N3784	Ref-Di	6,5V,3%,0,4W	31a	-	BZV14,BZV31,BZV94,1N4584
1N3785	Z-Di	6,8V,20%,1,5W	2c$	USA,Mot	-
1N3785A...3820A	Z-Di	=1N3785..3820:10%	2c$	-	-
1N3785A..3820A	Z-Di	=1N3785..3820:10%	2c$	-	-
1N3785B...3820B	Z-Di	=1N3785..3820:5%	2c$	-	-
1N3785B..3820B	Z-Di	=1N3785..3820:5%	2c$	-	-
1N3786	Z-Di	=1N3785:7,5V	2c$	-	-
1N3787	Z-Di	=1N3785:8,2V	2c$	-	-
1N3788	Z-Di	=1N3785:9,1V	2c$	-	-
1N3789	Z-Di	=1N3785:10V	2c$	-	-
1N379	Z-Di	8,2V,0,15W	31a	USA	BZX55/..,BZX79/..,ZPD..,1N5237..81,..
1N3790	Z-Di	=1N3785:11V	2c$	-	-
1N3791	Z-Di	=1N3785:12V	2c$	-	-
1N3792	Z-Di	=1N3785:13V	2c$	-	-
1N3793	Z-Di	=1N3785:15V	2c$	-	-
1N3794	Z-Di	=1N3785:16V	2c$	-	-
1N3795	Z-Di	=1N3785:18V	2c$	-	-

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1N3796	Z-Di	=1N3785:20V	2c$	-	-
1N3797	Z-Di	=1N3785:22V	2c$	-	-
1N3798	Z-Di	=1N3785:24V	2c$	-	-
1N3799	Z-Di	=1N3785:27V	2c$	-	-
1N38	Ge-Di	Uni,120V,50mA	31a	USA,Nec,Tho	AA117..118,AA132..133
1N380	Z-Di	=1N379:10V	31a	-	-
1N3800	Z-Di	=1N3785:30V	2c$	-	-
1N3801	Z-Di	=1N3785:33V	2c$	-	-
1N3802	Z-Di	=1N3785:36V	2c$	-	-
1N3803	Z-Di	=1N3785:39V	2c$	-	-
1N3804	Z-Di	=1N3785:43V	2c$	-	-
1N3805	Z-Di	=1N3785:47V	2c$	-	-
1N3806	Z-Di	=1N3785:51V	2c$	-	-
1N3807	Z-Di	=1N3785:56V	2c$	-	-
1N3808	Z-Di	=1N3785:62V	2c$	-	-
1N3809	Z-Di	=1N3785:68V	2c$	-	-
1N381	Z-Di	=1N379:12V	31a	-	-
1N3810	Z-Di	=1N3785:75V	2c$	-	-
1N3811	Z-Di	=1N3785:82V	2c$	-	-
1N3812	Z-Di	=1N3785:91V	2c$	-	-
1N3813	Z-Di	=1N3785:100V	2c$	-	-
1N3814	Z-Di	=1N3785:110V	2c$	-	-
1N3815	Z-Di	=1N3785:120V	2c$	-	-
1N3816	Z-Di	=1N3785:130V	2c$	-	-
1N3817	Z-Di	=1N3785:150V	2c$	-	-
1N3818	Z-Di	=1N3785:160V	2c$	-	-
1N3819	Z-Di	=1N3785:180V	2c$	-	-
1N382	Z-Di	=1N379:15V	31a	-	-
1N3820	Z-Di	=1N3785:200V	2c$	-	-
1N3821	Z-Di	3,3V,10%,1W	34a	USA,Sie,Tho	BZW22/..,BZX61/..,ZPY..,1N5913..22,+
1N3821A..3830A	Z-Di	=1N3821..3830:5%	34a	-	-
1N3821A..3830A	Z-Di	=1N3821..3830:5%	34a	-	-
1N3822	Z-Di	=1N3821:3,6V	34a	-	-
1N3823	Z-Di	=1N3821:3,9V	34a	-	-
1N3824	Z-Di	=1N3821:4,3V	34a	-	-
1N3825	Z-Di	=1N3821:4,7V	34a	-	-
1N3826	Z-Di	=1N3821:5,1V	34a	-	-
1N3827	Z-Di	=1N3821:5,6V	34a	-	-
1N3828	Z-Di	=1N3821:6,2V	34a	-	-
1N3829	Z-Di	=1N3821:6,8V	34a	-	-
1N383	Z-Di	=1N379:18V	31a	-	-
1N3830	Z-Di	=1N3821:7,5V	34a	-	-
1N3831	Trigger-Di	Ub=16..24V,Ib<0,125mA,Itsm=5A	31a	USA,Itt	4E20..,4E20M..
1N3832	Trigger-Di	=1N3831:Ub=21..29V	31a	-	-
1N3833	Trigger-Di	=1N3831:Ub=26..34V	31a	-	4E30..,4E30M..
1N3834	Trigger-Di	=1N3831:Ub=31..39V	31a	-	4E40..,4E40M..
1N3835	Trigger-Di	=1N3831:Ub=36..44V	31a	-	4E40..,4E40M..
1N3836	Trigger-Di	=1N3831:Ub=41..49V	31a	-	4E50..,4E50M..
1N3837	Trigger-Di	=1N3831:Ub=46..54V	31a	-	4E50..,4E50M..
1N3838	Trigger-Di	=1N3831:Ub=90..110V	31a	-	4E100..,4E100M..
1N3839	Trigger-Di	=1N3831:Ub=16..24V	31a	-	4E20..,4E20M..
1N384	Z-Di	=1N379:22V	31a	-	-
1N3840	Trigger-Di	=1N3831:Ub=21..29V	31a	-	-
1N3841	Trigger-Di	=1N3831:Ub=26..34V	31a	-	4E30..,4E30M..
1N3842	Trigger-Di	=1N3831:Ub=31..39V	31a	-	4E40..,4E40M..
1N3843	Trigger-Di	=1N3831:Ub=36..44V	31a	-	4E40..,4E40M..
1N3844	Trigger-Di	=1N3831:Ub=41..49V	31a	-	4E50..,4E50M..
1N3845	Trigger-Di	=1N3831:Ub=46..54V	31a	-	4E50..,4E50M..
1N3846	Trigger-Di	=1N3831:Ub=90..110V	31a	-	4E100..,4E100M..
1N3847	Ge-Di	Tunnel-Di,10mA,Ip=5mA,<25pF,<3e	-	Kmc	-
1N3848	Ge-Di	Tunnel-Di,18mA,Ip=10mA,<25pF,<2,5e	-	Kmc	-
1N3849	Ge-Di	Tunnel-Di,35mA,Ip=20mA,<30pF,<2e	-	Kmc	-
1N385	Z-Di	=1N379:27V	31a	-	-
1N3850	Ge-Di	Tunnel-Di,85mA,Ip=50mA,<40pF,<1,5e	-	Kmc	-

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1N3851	Ge-Di	Tunnel-Di,170mA,Ip=100mA,<40pF,<1e	-	Kmc	-
1N3852	Ge-Di	Tunnel-Di,10mA,Ip=5mA,<15pF,<3e	-	Kmc	-
1N3853	Ge-Di	Tunnel-Di,18mA,Ip=10mA,<15pF,<2,5e	-	Kmc	-
1N3854	Ge-Di	Tunnel-Di,35mA,Ip=20mA,<20pF,<2e	-	Kmc	-
1N3855	Ge-Di	Tunnel-Di,85mA,Ip=50mA,<25pF,<1,5e	-	Kmc	-
1N3856	Ge-Di	Tunnel-Di,170mA,Ip=100mA,<25pF,<1e	-	Kmc	-
1N3857	Ge-Di	Tunnel-Di,10mA,Ip=5mA,<8pF,<3e	-	Kmc	-
1N3858	Ge-Di	Tunnel-Di,18mA,Ip=10mA,<8pF,<2,5e	-	Kmc	-
1N3859	Ge-Di	Tunnel-Di,35mV,Ip=20mA,<10pF,<2e	-	Kmc	-
1N386	Z-Di	=1N379:33V	31a	-	-
1N3860	Ge-Di	Tunnel-Di,85mA,Ip=50mA,<12pF,<1,5e	-	Kmc	-
1N3861	Ge-Di	Tunnel-Di	-	Kmc	-
1N3862	Ge-Di	Tunnel-Di,10mA,<4pF	-	Kmc	-
1N3863	Ge-Di	Tunnel-Di	-	Kmc	-
1N3864	Si-Di	S,125V,<5pF(0V),<900ns	31a	USA	BA173,BAV19..21,BAX15..17,+
1N3865	Ge-Di	Uni,80V	31a	Idc,Sem	1N270
1N3866	Si-Di	Gl,200V,1A	31a	USA	BY126..127,BY133..134,1N4003..07,+
1N3867	Si-Di	=1N3866:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N3868	Si-Di	=1N3866:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N3869	Si-Di	Gl,1000V,0,5A	31a	USA	BA159,BY127,BY133,1N4007,+
1N387	Z-Di	=1N379:39V	31a	-	-
1N3870	Si-Di	=1N3879:1500V	31a	-	BY269,DM513,EM516,GP10W,+
1N3871	Si-Di	=1N3879:2000V,0,25A	31a	-	BAY91,BY203/20,SHG2
1N3872	Si-Di	S,90V,<5pF(0V),<15ns	31a	USA	BA202..203,BAV16,BAY43
1N3873	Si-Di	SS,90V,0,15A,<4pF(0V),<4ns	31a	USA	BA219,BAW47
1N3874	Si-Di	=1N3879:Iso	32a	USA	-
1N3875	Si-Di	=1N3880:Iso	32a	-	-
1N3876	Si-Di	=1N3881:Iso	32a	-	-
1N3877	Si-Di	=1N3882:Iso	32a	-	-
1N3878	Si-Di	=1N3883:Iso	32a	-	-
1N3879(A)	Si-Di	Gl/S-L,50V,6A(Tc=100o),<200ns	32a$	USA,Mot,Rca	BYX62/800
1N3879R...3883R	Si-Di	=1N3879:	32b&	-	BYX62/800R
1N3879R..3883R	Si-Di	-	32b&	-	BYX62/800R
1N388	Z-Di	=1N379:47V	31a	-	-
1N3880(A)	Si-Di	=1N3879:100V	32a$	-	BYX62/800
1N3881(A)	Si-Di	=1N3879:200V	32a$	-	BYX62/800
1N3882(A)	Si-Di	=1N3879:300V	32a$	-	BYX62/800
1N3883(A)	Si-Di	=1N3879:400V	32a$	-	BYX62/800
1N3884	Si-Di	=1N3889:Iso	32a	USA	-
1N3885	Si-Di	=1N3890:Iso	32a	-	-
1N3886	Si-Di	=1N3891:Iso	32a	-	-
1N3887	Si-Di	=1N3892:Iso	32a	-	-
1N3888	Si-Di	=1N3893:Iso	32a	-	-
1N3889(A)	Si-Di	Gl/S-L,50V,12A(Tc=100o),<200ns	32a$	USA,Mot,Rca	BYX62/800
1N3889R...3893R	Si-Di	=1N3889:	32b&	-	BYX62/800R
1N3889R..3893R	Si-Di	-	32b&	-	BYX62/800R
1N389	Z-Di	=1N379:56V	31a	-	-
1N3890(A)	Si-Di	=1N3889:100V	32a$	-	BYX62/800
1N3891(A)	Si-Di	=1N3889:200V	32a$	-	BYX62/800
1N3892(A)	Si-Di	=1N3889:300V	32a$	-	BYX62/800
1N3893(A)	Si-Di	=1N3889:400V	32a$	-	BYX62/800
1N3894	Si-Di	Gl,Uni,400V,0,4A	31a	Sem,Ssi	BA157..159,BY204/4,BY207,+
1N3895	Si-Di	Gl,Uni,350V,0,4A	31a	Sem,Ssi	BA157..159,BY204/4,BY206..207,+
1N3896	Z-Di	0,775V,5%,0,25W	31a	Idc,Sem	-
1N3897	Z-Di	1,5V,5%,0,25W	31a	Idc,Sem	-
1N3898	Z-Di	2V,5%,0,25W	31a	Idc,Sem	-
1N3899	Si-Di	Gl/S-L,50V,20A(Tc=100o),<200ns	32a$	USA,Phi,Tho	BYT65/600,1N3909..13
1N3899R...3903R	Si-Di	=1N3899:400V	32b&	-	BYT65/600R,1N3909R..13R
1N3899R..3903R	Si-Di	-	32b&	-	BYT65/600R,1N3909R..13R
1N39	Ge-Di	Uni,200V,50mA	31a	USA,Nec,Tho	-
1N390	Z-Di	=1N379:68V	31a	-	-
1N3900	Si-Di	=1N3899:100V	32a$	-	BYT65/600,1N3910..13
1N3901	Si-Di	=1N3899:200V	32a$	-	BYT65/600,1N3911..13
1N3902	Si-Di	=1N3899:300V	32a$	-	BYT65/600,1N3912..13

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1N3903	Si-Di	=1N3899:400V	32a$	-	BYT65/600,1N3913
1N3904	Si-Di	=1N3899:Iso	32a$	Sem,Ssi	1N3914..18
1N3905	Si-Di	=1N3900:Iso	32a$	-	1N3915..18
1N3906	Si-Di	=1N3901:Iso	32a$	-	1N3916..18
1N3907	Si-Di	=1N3902:Iso	32a$	-	1N3917..18
1N3908	Si-Di	=1N3903:Iso	32a$	-	1N3918
1N3909	Si-Di	Gl/S-L,50V,30A(Tc=100o),<200ns	32a$	USA,Phi,Tho	MR860..866
1N3909R...3913R	Si-Di	=1N3909..3913:	32b&	-	MR864R..866R
1N3909R..3913R	Si-Di	-	32b&	-	MR864R..866R
1N391	Z-Di	=1N379:82V	31a	-	-
1N3910	Si-Di	=1N3909:100V	32a$	-	MR861..866
1N3911	Si-Di	=1N3909:200V	32a$	-	MR862..866
1N3912	Si-Di	=1N3909:300V	32a$	-	MR864..866
1N3913	Si-Di	=1N3909:400V	32a$	-	MR864..866
1N3914	Si-Di	=1N3909:Iso	32a	-	-
1N3915	Si-Di	=1N3910:Iso	32a	-	-
1N3916	Si-Di	=1N3911:Iso	32a	-	-
1N3917	Si-Di	=1N3912:Iso	32a	-	-
1N3918	Si-Di	=1N3913:Iso	32a	-	-
1N3919	Si-Di	Gl-L,1000V,5A(Tc=100o)	32a$	USA	BYX38/1200,BYX39/1200
1N392	Z-Di	=1N379:100V	31a	-	-
1N3920	Si-Di	=1N3919:1500V	32a$	-	-
1N3921	Si-Di	=1N3919:2000V	32a$	-	-
1N3922	Si-Di	=1N3919:2500V	32a$	-	-
1N3923	Si-Di	=1N3919:3000V	32a$	-	-
1N3924	Si-Di	Gl-L,1000V,10A(Tc=100o)	32a$	USA	BYX42/1200,BYX98/1200
1N3925	Si-Di	=1N3924:1500V	32a$	-	-
1N3926	Si-Di	=1N3924:2000V	32a$	-	-
1N3927	Si-Di	=1N3924:2500V	32a$	-	-
1N3928	Si-Di	=1N3924:3000V	32a$	-	-
1N3929	Si-Di	Gl,1000V,1A	34a	USA	BY127,BY133,BY227,1N4007,+
1N393	Z-Di	=1N379:120V	31a	-	-
1N3930	Si-Di	=1N3929:1500V	34a	-	BY269,DM513,EM516,GP10W
1N3931	Si-Di	=1N3929:2000V	34a	-	-
1N3932	Si-Di	=1N3929:2500V	34a	-	-
1N3933	Si-Di	=1N3929:3000V	34a	-	-
1N3934	Si-Di	Gl-L,1200V,10A	32a$	USA	BYX42/1200,BYX98/1200
1N3935	Trigger-Di	Ub=26..34V,Ib<15?A,Itsm=10A	31a	Spe	-
1N3936	Trigger-Di	Ub=16..24V,Ib<0,125mA,Itsm=10A	31a	Spe	-
1N3937	Trigger-Di	Ub=90..110V,Ib<0,125mA,Itsm=10A	31a	Itt	-
1N3938	Si-Di	Gl,contr.av.,200V,2A	34a	USA,Tho	BYW52..56,1N5060..62
1N3939	Si-Di	=1N3938:400V	34a	-	BYW53..56,1N5060..62
1N394	Z-Di	=1N379:150V	31a	-	-
1N3940	Si-Di	=1N3938:600V	34a	-	BYW54..56,1N5061..62
1N3941	Si-Di	=1N3938:800V	34a	-	BYW55..56,1N5062
1N3942	Si-Di	=1N3938:1000V	34a	-	BYW56
1N3943	Z-Di	2,5V,0,75W	34a	Sol	-
1N3944	Ge-Di	S,15V,<1,5pF(0V),<12ns	31a	USA	AAY48,1N995
1N3945	Si-Di	VHF-Tuning,20V,20pF(4V)	31a	Gen,Trw	-
1N3946	Si-Di	VHF-Tuning,9V,71pF(4V)	31a	Gen,Trw	-
1N3947	Si-Di	VHF-Tuning,9V,70pF(4V)	31a	Gen,Trw	-
1N3948	Si-Di	Tunnel-Di,Ip=4,7mA,Up=80mV,Ip/Iv>3,5	-		-
1N3949	Z-Di	20V,5%,10W(Tc=25o)	32a	USA,Sie	BZX98/C20,BZY93/C20,ZX20,1N2984,+
1N395	Z-Di	=1N379:180V	31a	-	-
1N3950	Z-Di	20V,5%,1,5W	2c	USA	-
1N3951	Z-Di	25V,5%,1,5W	2c	USA	-
1N3952	Si-Di	Gl,130V,0,2A	31a	Sem	BA189..190,BAY20..21,BAY45..46,+
1N3953	Ge-Di	S,40V,<300ns	31a	Idc,Sem	AAY28,1N631,1N633
1N3954	Si-Di	SS,50V,<3,2pF(0V),<4ns	31a	Idc,Msc,Sem	BAW62,BAX95,1N4148..49,1N4446..49+
1N3955	Si-Di	Gl-L,100V,70A(Tc=150o)	32	old	-
1N3956	Si-Di	SS,30V,2pF(0V),2ns	31a	Idc,Sem	BA218,BAX13,BAX91,1N4148..49,+
1N3957(GP)	Si-Di	=1N3611:1000V	31a	USA,Sie	BY127,BY133,BY227,1N4007,+
1N3958(C)	Si-Di	Gl/S-L,100V,3,5A	32a$	USA	BYX38/300,BYX39/600
1N3959(C)	Si-Di	=1N3958:200V	32a$	-	BYX38/300,BYX39/600

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1N396	Z-Di	=1N379:220V	31a	-	-
1N3960(C)	Si-Di	=1N3958:300V	32a$	-	BYX38/300,BYX39/600
1N3961(C)	Si-Di	=1N3958:400V	32a$	-	BYX38/600,BYX39/600
1N3962(C)	Si-Di	=1N3958:500V	32a$	-	BYX38/600,BYX39/600
1N3963(C)	Si-Di	=1N3958:600V	32a$	-	BYX38/600,BYX39/600
1N3964	Si-Di	Gl-L,contr.av.,200V,22A(Tc=120o)	32a$	USA	BYX25/600
1N3965	Si-Di	=1N3964:400V	32a$	-	BYX25/600
1N3966	Si-Di	=1N3964:600V	32a$	-	BYX25/600
1N3967	Si-Di	=1N3964:800V	32a$	-	BYX25/800
1N3968	Si-Di	Gl-L,contr.av.,200V,50A(Tc=120o)	32a$	USA	-
1N3969	Si-Di	=1N3968:400V	32a$	-	-
1N397	Z-Di	=1N379:270V	31a	-	-
1N3970	Si-Di	=1N3968:600V	32a$	-	-
1N3971	Si-Di	=1N3968:800V	32a$	-	-
1N3972	Si-Di	Gl-L,contr.av.,200V,104A(Tc=120o)	73a$	USA	-
1N3973	Si-Di	=1N3972:400V	73a$	-	-
1N3974	Si-Di	=1N3972:600V	73a$	-	-
1N3975	Si-Di	=1N3972:800V	73a$	-	-
1N3976	Si-Di	Gl-L,contr.av.,200V,250A(Tc=120o)	73a$	USA	-
1N3977	Si-Di	=1N3976:400V	73a$	-	-
1N3978	Si-Di	=1N3976:600V	73a$	-	-
1N3979	Si-Di	=1N3976:800V	73a$	-	-
1N398	Z-Di	=1N379:330V	31a	-	-
1N3981	Si-Di	Gl,Uni,200V,3A	31a	USA	BY251..255,BYW17/200,1N5402..08,+
1N3982	Si-Di	=1N3981:400V	31a	-	BY252..255,BYW17/400,1N5404..08,+
1N3983	Si-Di	=1N3981:600V	31a	-	BY253..255,BYW17/400,1N5406..08,+
1N3984	Z-Di	5,5V,5%,10W	32a	USA,Sie	BZX98/C5V6,BZY93/C5V6,ZX5,6,1N3997,+
1N3985	Z-Di	=1N3984:6V	32a	-	BZX98/C6V2,BZY93/C6V2,ZX6,2,1N3998,+
1N3986	Z-Di	=1N3984:6,2V	32a	-	BZX98/C6V2,BZY93/C6V2,ZX6,2,1N3998,+
1N3987	Si-Di	Gl-L,700V,6A(Tc=150o)	32a$	USA,Tho	BYX38/900,BYX39/800
1N3987R...3990R	Si-Di	=1N3987..3990:	32b&	-	BYX38/..R,BYX39/..R
1N3987R..3990R	Si-Di	-	32b&	-	BYX38/..R,BYX39/..R
1N3988	Si-Di	=1N3987:800V	32a$	-	BYX38/900,BYX39/800
1N3989	Si-Di	=1N3987:900V	32a$	-	BYX38/900,BYX39/1000
1N399	Z-Di	=1N379:390V	31a	-	-
1N3990	Si-Di	=1N3987:1000V	32a$	-	BYX38/1200,BYX39/1000
1N3991	Ge-Di	Uni,35V	31a	Idc,Sem	AA117..118,AA132..134,1N34,1N54,+
1N3992	Si-Di	kV-Gl,4kV	31a	Edl,Sem	GP02-40,MR250-4,1N1734A
1N3993	Z-Di	3,9V,10%,10W(Tc=55o)	32a$	USA,Mot,Sie	BZX98/..,BZY93/..,ZL..,ZX..
1N3993A...4000A	Z-Di	=1N3993..4000:5%	32a$	-	-
1N3993A..4000A	Z-Di	=1N3993..4000:5%	32a$	-	-
1N3994	Z-Di	=1N3993:4,3V	32a$	-	-
1N3995	Z-Di	=1N3993:4,7V	32a$	-	-
1N3996	Z-Di	=1N3993:5,1V	32a$	-	-
1N3997	Z-Di	=1N3993:5,6V	32a$	-	-
1N3998	Z-Di	=1N3993:6,2V	32a$	-	-
1N3999	Z-Di	=1N3993:6,8V	32a$	-	-
1N40	Ge-Di	4xHF-Dem,gep,25V,225mA	4x31a	Kem,Spe	-
1N400	Z-Di	=1N379:470V	31a	-	-
1N4000	Z-Di	=1N3993:7,5V	32a$	-	-
1N4001	Si-Di	Gl,Uni,50V,1A	31a	USA,EUR,JAP	BY126..127,BY133..135,1N5614..22,+
1N4001..4007D	Si-Di	-	31a	Philips	-
1N4002	Si-Di	-	72	Philips	-
1N4002(..)	Si-Di	=1N4001:100V	31a	-	BY126..127,BY133..135,1N5614..22,+
1N4003(..)	Si-Di	=1N4001:200V	31a	-	BY126..127,BY133..134,1N5614..22,+
1N4004(..)	Si-Di	=1N4001:400V	31a	-	BY126..127,BY133..134,1N5616..22,+
1N4005(..)	Si-Di	=1N4001:600V	31a	-	BY126..127,BY133..134,1N5618..22,+
1N4006(..)	Si-Di	=1N4001:800V	31a	-	BY127,BY133,BY227,1N5620..22,+
1N4007(..)	Si-Di	=1N4001:1000V	31a	-	BY127,BY133,BY227,1N5622,+
1N4007KH	Si-Di	=1N4001:1600V	31a	-	DM513,DM516,EM516,GP10Y
1N4007KS	Si-Di	=1N4001:1250V	31a	-	BY133,BYX95,EM513,GP10V,+
1N4008	Ge-Di	S,12V,0,1A,<1pF(0V),<70ns	31a	USA	AAZ18
1N4009	Si-Di	SS,35V,0,1A,<4pF(0V),<4ns	31a	USA,Phi,Tho	BA318,BAY38,BAX80,1N4148..49,+
1N401	Si-St	1,5V	2c	Syl	-

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1N4010	Ref-Di	6,2V,5%,0,4W	31a	USA,Sie	BZV10,BZV27,BZX90,1N4580
1N4011	Si-Di	Gl,1000V,0,5A	34a	Sem,Ssi	BA159,BY127,BY133,1N4007,+
1N4012	Si-Di	Gl-L,700V,12A(Tc=150o)	32a$	USA	BYW88/800,BYX80..81,1N4509..11,+
1N4013	Si-Di	=1N4012:800V	32a$	-	BYW88/800,BYX80..81,1N4509..11,+
1N4014	Si-Di	=1N4012:900V	32a$	-	BYW88/1000,BYX81,1N4510..11,+
1N4015	Si-Di	=1N4012:1000V	32a$	-	BYW88/1000,BYX81,1N4510..11,+
1N4016	Z-Di	8,2V,20%,5W(Tc=25o)	?32	USA	(BZX98/..,BZY93/..,ZX..,1N2972..3005)
1N4016A..4042A	Z-Di	=1N4016..4042:10%	?32	-	-
1N4016A..4042A	Z-Di	=1N4016..4042:10%	?32	-	-
1N4016B..4042B	Z-Di	=1N4016..4042:5%	?32	-	-
1N4016B..4042B	Z-Di	=1N4016..4042:5%	?32	-	-
1N4017	Z-Di	=1N4016:9,1V	?32	-	-
1N4018	Z-Di	=1N4016:10V	?32	-	-
1N4019	Z-Di	=1N4016:11V	?32	-	-
1N402	Si-St	2V	2c	-	-
1N4020	Z-Di	=1N4016:12V	?32	-	-
1N4021	Z-Di	=1N4016:13V	?32	-	-
1N4022	Z-Di	=1N4016:15V	?32	-	-
1N4023	Z-Di	=1N4016:16V	?32	-	-
1N4024	Z-Di	=1N4016:18V	?32	-	-
1N4025	Z-Di	=1N4016:20V	?32	-	-
1N4026	Z-Di	=1N4016:22V	?32	-	-
1N4027	Z-Di	=1N4016:24V	?32	-	-
1N4028	Z-Di	=1N4016:27V	?32	-	-
1N4029	Z-Di	=1N4016:30V	?32	-	-
1N403	Si-St	2,5V	2c	-	-
1N4030	Z-Di	=1N4016:33V	?32	-	-
1N4031	Z-Di	=1N4016:36V	?32	-	-
1N4032	Z-Di	=1N4016:39V	?32	-	-
1N4033	Z-Di	=1N4016:43V	?32	-	-
1N4034	Z-Di	=1N4016:47V	?32	-	-
1N4035	Z-Di	=1N4016:51V	?32	-	-
1N4036	Z-Di	=1N4016:56V	?32	-	-
1N4037	Z-Di	=1N4016:62V	?32	-	-
1N4038	Z-Di	=1N4016:68V	?32	-	-
1N4039	Z-Di	=1N4016:75V	?32	-	-
1N404	Si-St	3,1V	2c	-	-
1N4040	Z-Di	=1N4016:82V	?32	-	-
1N4041	Z-Di	=1N4016:91V	?32	-	-
1N4042	Z-Di	=1N4016:100V	?32	-	-
1N4043	Si-Di	Min,SS,25V,<4pF(0V),<4ns	?31a	Idc	(BA218,BAX13,BAX91,1N4148..49,++)
1N4044	Si-Di	Gl-L,50V,27SA(Tc=120o)	73a$	USA	-
1N4044R..4056R	Si-Di	=1N4044..4056:	73b&	-	-
1N4045	Si-Di	=1N4044:100V	73a$	-	-
1N4046	Si-Di	=1N4044:150V	73a$	-	-
1N4047	Si-Di	=1N4044:200V	73a$	-	-
1N4048	Si-Di	=1N4044:250V	73a$	-	-
1N4049	Si-Di	=1N4044:300V	73a$	-	-
1N405	Si-St	3,7V	2c	-	-
1N4050	Si-Di	=1N4044:400V	73a$	-	-
1N4051	Si-Di	=1N4044:500V	73a$	-	-
1N4052	Si-Di	=1N4044:600V	73a$	-	-
1N4053	Si-Di	=1N4044:700V	73a$	-	-
1N4054	Si-Di	=1N4044:800V	73a$	-	-
1N4055	Si-Di	=1N4044:900V	73a$	-	-
1N4056	Si-Di	=1N4044:1000V	73a$	-	-
1N4057(A)	Ref-Di	12,4V,5%,1,5W	31a	USA,Mot,Sie	-
1N4058(A)	Ref-Di	=1N4057:14,6V	31a	-	-
1N4059(A)	Ref-Di	=1N4057:16,8V	31a	-	-
1N406	Si-St	4,3V	2c	-	-
1N4060(A)	Ref-Di	=1N4057:18,5V	31a	-	-
1N4061(A)	Ref-Di	=1N4057:21V	31a	-	-
1N4062(A)	Ref-Di	=1N4057:23V	31a	-	-
1N4063(A)	Ref-Di	=1N4057:27V	31a	-	-

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1N4064(A)	Ref-Di	=1N4057:30V	31a	-	-
1N4065(A)	Ref-Di	=1N4057:33V	31a	-	-
1N4066(A)	Ref-Di	=1N4057:37V	31a	-	-
1N4067(A)	Ref-Di	=1N4057:43V	31a	-	-
1N4068(A)	Ref-Di	=1N4057:47V	31a	-	-
1N4069(A)	Ref-Di	51V,5%,2W	31a	-	-
1N407	Si-St	5,2V	2c	-	-
1N4070(A)	Ref-Di	=1N4069:56V	31a	-	-
1N4071(A)	Ref-Di	=1N4069:62V	31a	-	-
1N4072(A)	Ref-Di	=1N4069:68V	31a	-	-
1N4073(A)	Ref-Di	=1N4069:75V	31a	-	-
1N4074(A)	Ref-Di	=1N4069:82V	31a	-	-
1N4075(A)	Ref-Di	=1N4069:87V	31a	-	-
1N4076(A)	Ref-Di	=1N4069:91V	31a	-	-
1N4077(A)	Ref-Di	=1N4069:100V	31a	-	-
1N4078(A)	Ref-Di	=1N4069:105V	31a	-	-
1N4079(A)	Ref-Di	=1N4069:110V	31a	-	-
1N408	Si-St	6,2V	2c	-	-
1N4080(A)	Ref-Di	=1N4069:120V	31a	-	-
1N4081(A)	Ref-Di	130V,5%,2,5W	31a	-	-
1N4082(A)	Ref-Di	=1N4081:140V	31a	-	-
1N4083(A)	Ref-Di	=1N4081:150V	31a	-	-
1N4084(A)	Ref-Di	=1N4081:175V	31a	-	-
1N4085(A)	Ref-Di	=1N4081:200V	31a	-	-
1N4086	Si-Di	5,70V,<10pF(0V),<200ns	31a	USA	BAW49..50,BAX15..17,BAY72,+
1N4087	Si-Di	55,50V,<1,8pF(0V),<2,5ns	31a	USA	BA318,BAY38,BAY95,1N4148..49,+
1N4088	Ge-Di	Uni,30V,0,55pF(10V)	31a	USA	AA117..118,AA132..14,1N34,1N54,+
1N4089	Si-Di	Gl,400V,1,1A	31a	USA	BY126..127,BY133..134,1N4004..07,+
1N409	Si-St	-	2c	-	-
1N4090	Ge-Di	Tunnel-Di,Ip=160?A,Up=62mV,Ip/Iv>4	34a	Gen	-
1N4091	Si-Di	UHF-Tuning,6V,4,2pF(0V),30GHz	Koax	Miv	-
1N4092	Si-Di	Uni,50V,10pF(6V)	31a	USA	BA127,BA187..190,1N4148..49,+
1N4093	Si-Di	Uni,50V,10pF(6V)	31a	USA	BA127,BA187..190,1N4148..49,+
1N4094	Z-Di	9,4V,2%,1W	-	Gsi	-
1N4095	Z-Di	5V,10%,0,33W	31a	USA,Sie	BZX55/C5V1,BZX79/C5V1,ZPD5,1,1N5231+
1N4096	Z-Di	90V,5%,3W	31a	USA	BZT03/..
1N4097	Z-Di	=1N4096:100V	31a	-	-
1N4098	Z-Di	=1N4096:150V	31a	-	-
1N4099	Z-Di	6,8V,5%,0,4W,ra	31a	USA,Sie,Tho	BZV39/..
1N41	Ge-Di	4xHF-Dem,gep,32V	-	Kem,Spe	-
1N410	Si-Di	-		Syl	-
1N4100	Z-Di	=1N4099:7,5V	31a	-	-
1N4101	Z-Di	=1N4099:8,2V	31a	-	-
1N4102	Z-Di	=1N4099:8,7V	31a	-	-
1N4103	Z-Di	=1N4099:9,1V	31a	-	-
1N4104	Z-Di	=1N4099:10V	31a	-	-
1N4105	Z-Di	=1N4099:11V	31a	-	-
1N4106	Z-Di	=1N4099:12V	31a	-	-
1N4107	Z-Di	=1N4099:13V	31a	-	-
1N4108	Z-Di	=1N4099:14V	31a	-	-
1N4109	Z-Di	=1N4099:15V	31a	-	-
1N411(A,B)	Si-Di	Gl-L,50V,25A,A:35A,B:50A	?32/a$	USA	BYX56/600,BYX97/300
1N4110	Z-Di	=1N4099:16V	31a	-	-
1N4111	Z-Di	=1N4099:17V	31a	-	-
1N4112	Z-Di	=1N4099:18V	31a	-	-
1N4113	Z-Di	=1N4099:19V	31a	-	-
1N4114	Z-Di	=1N4099:20V	31a	-	-
1N4115	Z-Di	=1N4099:22V	31a	-	-
1N4116	Z-Di	=1N4099:24V	31a	-	-
1N4117	Z-Di	=1N4099:25V	31a	-	-
1N4118	Z-Di	=1N4099:27V	31a	-	-
1N4119	Z-Di	=1N4099:28V	31a	-	-
1N412(A,B)	Si-Di	=1N411(A,B):100V	-		BYX56/600,BYX97/300
1N4120	Z-Di	=1N4099:30V	31a	-	-

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1N4121	Z-Di	=1N4099:33V	31a	-	-
1N4122	Z-Di	=1N4099:36V	31a	-	-
1N4123	Z-Di	=1N4099:39V	31a	-	-
1N4124	Z-Di	=1N4099:43V	31a	-	-
1N4125	Z-Di	=1N4099:47V	31a	-	-
1N4126	Z-Di	=1N4099:51V	31a	-	-
1N4127	Z-Di	=1N4099:56V	31a	-	-
1N4128	Z-Di	=1N4099:60V	31a	-	-
1N4129	Z-Di	=1N4099:62V	31a	-	-
1N413(A,B)	Si-Di	=1N411(A,B):200V	-		BYX56/600,BYX97/300
1N4130	Z-Di	=1N4099:68V	31a	-	-
1N4131	Z-Di	=1N4099:75V	31a	-	-
1N4132	Z-Di	=1N4099:82V	31a	-	-
1N4133	Z-Di	=1N4099:87V	31a	-	-
1N4134	Z-Di	=1N4099:91V	31a	-	-
1N4135	Z-Di	=1N4099:100V	31a	-	-
1N4136	Si-Di	Gl-L,200V,70A(Tc=100o)	32a$	USA	-
1N4137	Si-Di	=1N4136:400V	32a$	-	-
1N4138	Si-Di	=1N4136:600V	32a$	-	-
1N4139	Si-Di	Gl,50V,3A	31a	USA	BY251..255,BYW17/100,1N5400..08,+
1N4140	Si-Di	=1N4139:100V	31a	-	BY251..255,BYW17/100,1N5401..08,+
1N4141	Si-Di	=1N4139:200V	31a	-	BY251..255,BYW17/200,1N5402..08,+
1N4142	Si-Di	=1N4139:400V	31a	-	BY252..255,BYW17/400,1N5404..08,+
1N4143	Si-Di	=1N4139:600V	31a	-	BY253..255,BYW17/600,1N5406..08,+
1N4144	Si-Di	=1N4139:800V	31a	-	BY254..255,BYW17/800,1N5407..08,+
1N4145	Si-Di	=1N4139:1000V	31a	-	BY255,BYW17/1000,1N5408,+
1N4146	Si-Di	=1N4139:1200V	31a	-	BY255,BY228,BYW17/1200
1N4147	Si-Di	S,30V,<6pF(0V),10ns	31a	USA	BA218,BAX13,BAX91,1N4148..49,+
1N4148	Si-Di	SS,100V,0,2A,<4pF(0V),<4ns	31a	USA,EUR,JAP	BAW62,BAW76,BAX95,1N4446..49,+
1N4148W	Si-Di	=1N4148:SMD	71a(2,7mm)	Gsl	MMSD914
1N4148WS	Si-Di	=1N4148:SMD	71a(1,7mm)	Gsl	(BAS16-03W,BAS316)
1N4149	Si-Di	SS,100V,0,2A,<2pF(0V),<4ns	31a	-	BAW62,BAW76,BAX95,1N4446..49,+
1N415(A..H)	Si-Di	Schottky-Di,UHF,X-Band-M,9375MHz	Koax	USA	-
1N4150	Si-Di	SS,50V,0,2A,<2,5pF(0V),<4ns	31a	USA,EUR,JAP	BAW62,BAW76,BAX95,1N4148..49,+
1N4150W	Si-Di	=1N4150:SMD	71a(2,7mm)	Gsl	MMSD914
1N4151	Si-Di	SS,75V,0,2A,<2pF(0V),<4ns	31a	USA,EUR,JAP	BAW62,BAW76,BAX95,1N4148..49,+
1N4151W	Si-Di	=1N4151:SMD	71a(2,7mm)	Gsl	MMSD914
1N4152	Si-Di	SS,40V,0,2A,<2pF(0V),<4ns	31a	USA,EUR,JAP	BAW62,BAW76,BAX95,1N4148..49,+
1N4153	Si-Di	SS,75V,0,2A,<4ns	31a	-	BAW62,BAW76,BAX95,1N4148..49,+
1N4154	Si-Di	SS,35V,0,2A,<4pF(0V),<4ns	31a	USA,EUR,JAP	BAW62,BAW76,BAX95,1N4148..49,+
1N4155	Si-Di	S,Uni,400V,0,2A,<10?s	31a	USA	BA157..159,BA199/450,BAY89,+
1N4156	Si-St	1,41V(1mA),0,4W	31a	USA,Gen	BZ102/1V4,BZX75/C1V4,ZTE1,5
1N4157	Si-St	2,05V(1mA),0,4W	31a	-	BZ102/2V1,BZX75/C2V1,ZTE1
1N4158	Z-Di	6,8V,20%,1W	31a	USA,Fer,Tho	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1N4158A..4193A	Z-Di	=1N4158..4193:10%	31a	-	-
1N4158A..4193A	Z-Di	=1N4158..4193:10%	31a	-	-
1N4158B..4193B	Z-Di	=1N4158..4193:5%	31a	-	-
1N4158B..4193B	Z-Di	=1N4158..4193:5%	31a	-	-
1N4159	Z-Di	=1N4158:7,5V	31a	-	-
1N416(A..G)	Si-Di	UHF,S-Band-M,3060MHz	Koax	USA	-
1N4160	Z-Di	=1N4158:8,2V	31a	-	-
1N4161	Z-Di	=1N4158:9,1V	31a	-	-
1N4162	Z-Di	=1N4158:10V	31a	-	-
1N4163	Z-Di	=1N4158:11V	31a	-	-
1N4164	Z-Di	=1N4158:12V	31a	-	-
1N4165	Z-Di	=1N4158:13V	31a	-	-
1N4166	Z-Di	=1N4158:15V	31a	-	-
1N4167	Z-Di	=1N4158:16V	31a	-	-
1N4168	Z-Di	=1N4158:18V	31a	-	-
1N4169	Z-Di	=1N4158:20V	31a	-	-
1N417	Ge-Di	S,60V,60mA,<300ns	31a	USA	AAZ15,AAZ17,1N276
1N4170	Z-Di	=1N4158:22V	31a	-	-
1N4171	Z-Di	=1N4158:24V	31a	-	-
1N4172	Z-Di	=1N4158:27V	31a	-	-

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1N4173	Z-Di	=1N4158:30V	31a	-	-
1N4174	Z-Di	=1N4158:33V	31a	-	-
1N4175	Z-Di	=1N4158:36V	31a	-	-
1N4176	Z-Di	=1N4158:39V	31a	-	-
1N4177	Z-Di	=1N4158:43V	31a	-	-
1N4178	Z-Di	=1N4158:47V	31a	-	-
1N4179	Z-Di	=1N4158:51V	31a	-	-
1N418	Ge-Di	S,60V,16mA,<300ns	31a	USA	AAY28,1N191..192
1N4180	Z-Di	=1N4158:56V	31a	-	-
1N4181	Z-Di	=1N4158:62V	31a	-	-
1N4182	Z-Di	=1N4158:68V	31a	-	-
1N4183	Z-Di	=1N4158:75V	31a	-	-
1N4184	Z-Di	=1N4158:82V	31a	-	-
1N4185	Z-Di	=1N4158:91V	31a	-	-
1N4186	Z-Di	=1N4158:100V	31a	-	-
1N4187	Z-Di	=1N4158:110V	31a	-	-
1N4188	Z-Di	=1N4158:120V	31a	-	-
1N4189	Z-Di	=1N4158:130V	31a	-	-
1N419	Ge-Di	S,80V,60mA,<300ns	31a	USA	AAZ15
1N4190	Z-Di	=1N4158:150V	31a	-	-
1N4191	Z-Di	=1N4158:160V	31a	-	-
1N4192	Z-Di	=1N4158:180V	31a	-	-
1N4193	Z-Di	=1N4158:200V	31a	-	-
1N4194	Z-Di	6,8V,20%,10W	32a	Nae	BZX98/..,BZY93/..,ZX..,1N2970..3015
1N4194A..4239A	Z-Di	=1N4194..4239:10%	32a	-	-
1N4194A..4239A..	Z-Di	=1N4194..4239:10%	32a	-	-
1N4194B..4239B	Z-Di	=1N4194..4239:5%	32a	-	-
1N4194B..4239B..	Z-Di	=1N4194..4239:5%	32a	-	-
1N4195	Z-Di	=1N4194:7,5V	32a	-	-
1N4196	Z-Di	=1N4194:8,2V	32a	-	-
1N4197	Z-Di	=1N4194:9,1V	32a	-	-
1N4198	Z-Di	=1N4194:10V	32a	-	-
1N4199	Z-Di	=1N4194:11V	32a	-	-
1N42	Ge-Di	4xUni,115V,0,1A(ss)	4x31a	Kem,Spe	AA117..118,AA132..133
1N4200	Z-Di	=1N4194:12V	32a	-	-
1N4201	Z-Di	=1N4194:13V	32a	-	-
1N4202	Z-Di	=1N4194:14V	32a	-	-
1N4203	Z-Di	=1N4194:15V	32a	-	-
1N4204	Z-Di	=1N4194:16V	32a	-	-
1N4205	Z-Di	=1N4194:17V	32a	-	-
1N4206	Z-Di	=1N4194:18V	32a	-	-
1N4207	Z-Di	=1N4194:19V	32a	-	-
1N4208	Z-Di	=1N4194:20V	32a	-	-
1N4209	Z-Di	=1N4194:22V	32a	-	-
1N4210	Z-Di	=1N4194:24V	32a	-	-
1N4211	Z-Di	=1N4194:25V	32a	-	-
1N4212	Z-Di	=1N4194:27V	32a	-	-
1N4213	Z-Di	=1N4194:30V	32a	-	-
1N4214	Z-Di	=1N4194:33V	32a	-	-
1N4215	Z-Di	=1N4194:36V	32a	-	-
1N4216	Z-Di	=1N4194:39V	32a	-	-
1N4217	Z-Di	=1N4194:43V	32a	-	-
1N4218	Z-Di	=1N4194:45V	32a	-	-
1N4219	Z-Di	=1N4194:47V	32a	-	-
1N4220	Z-Di	=1N4194:50V	32a	-	-
1N4221	Z-Di	=1N4194:51V	32a	-	-
1N4222	Z-Di	=1N4194:52V	32a	-	-
1N4223	Z-Di	=1N4194:56V	32a	-	-
1N4224	Z-Di	=1N4194:62V	32a	-	-
1N4225	Z-Di	=1N4194:68V	32a	-	-
1N4226	Z-Di	=1N4194:75V	32a	-	-
1N4227	Z-Di	=1N4194:82V	32a	-	-
1N4228	Z-Di	=1N4194:91V	32a	-	-
1N4229	Z-Di	=1N4194:100V	32a	-	-

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1N4230	Z-Di	=1N4194:105V	32a	-	-
1N4231	Z-Di	=1N4194:110V	32a	-	-
1N4232	Z-Di	=1N4194:120V	32a	-	-
1N4233	Z-Di	=1N4194:130V	32a	-	-
1N4234	Z-Di	=1N4194:140V	32a	-	-
1N4235	Z-Di	=1N4194:150V	32a	-	-
1N4236	Z-Di	=1N4194:160V	32a	-	-
1N4237	Z-Di	=1N4194:175V	32a	-	-
1N4238	Z-Di	=1N4194:180V	32a	-	-
1N4239	Z-Di	=1N4194:200V	32a	-	-
1N4240	Z-Di	5V,2%,10W(Tc=25o)	32	Idc,Sie	BZX98/5V1,BZY93/C5V1,ZX5,1
1N4241	Z-Di	6V,2%,10W(Tc=25o)	32	Idc,Sie	BZX98/C6V2,BZY93/C6V2,ZX6,2
1N4242	Si-Di	2xSS,40V,<2pF(0V),<2ns	42	USA	-
1N4243	Si-Di	4xSS,40V,<2pF(0V),<2ns	-	USA	-
1N4244	Si-Di	SS,10V,0,05A,<0,8pF(0V),<0,75ns	31a	USA,Tho	BAY82,1N4376
1N4245(GP)	Si-Di	Gl,Uni,200V,1A	31a	USA,Sie	BY126..127,BY133..134,1N4003..07,+
1N4246(GP)	Si-Di	=1N4245:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N4247(GP)	Si-Di	=1N4245:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N4248(GP)	Si-Di	=1N4245:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N4249(GP)	Si-Di	=1N4245:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N424A	Si-Di	Uni,150V,0,225A(ss)	31a	Tho	BA147/150,BA190,1N5195..96,+
1N4250	Si-Di	Gl,800V,0,5A	31a	USA	BY127,BY133,BY227,1N4006..07,+
1N4251	Si-Di	=1N4250:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N4252	Si-Di	=1N4250:1200V	31a	-	BY127,BY133,BY227,BY268,GP10Q+
1N4253	Si-Di	=1N4250:1500V	31a	-	BY269,DM513,EM516,GP10W,+
1N4254	Si-Di	Gl,1500V,0,25A	31a	USA	BAY91,BY203/16,GP02-20,SHG1,5,+
1N4255	Si-Di	=1N4254:2000V	31a	-	BAY91,BY203/20,GP02-20,SHG2,+
1N4256	Si-Di	=1N4254:2500V	31a	-	GP02-30,MR250-3,SHG2,5
1N4257	Si-Di	=1N4254:3000V	31a	-	GP02-30,MR250-3,SHG2,5
1N4258	Z-Di	6,8V,20%,10W	21	Nae	(BZX98/..,BZY93/..,ZX..,1N2970..3015)
1N4258A..4293A	Z-Di	=1N4258..4293:10%	21	-	-
1N4258A..4293A	Z-Di	=1N4258..4293:10%	21	-	-
1N4258B..4293B	Z-Di	=1N4258..4293:5%	21	-	-
1N4258B..4293B	Z-Di	=1N4258..4293:5%	21	-	-
1N4259	Z-Di	=1N4258:7,5V	21	-	-
1N4260	Z-Di	=1N4258:8,2V	21	-	-
1N4261	Z-Di	=1N4258:9,1V	21	-	-
1N4262	Z-Di	=1N4258:10V	21	-	-
1N4263	Z-Di	=1N4258:11V	21	-	-
1N4264	Z-Di	=1N4258:12V	21	-	-
1N4265	Z-Di	=1N4258:13V	21	-	-
1N4266	Z-Di	=1N4258:15V	21	-	-
1N4267	Z-Di	=1N4258:16V	21	-	-
1N4268	Z-Di	=1N4258:18V	21	-	-
1N4269	Z-Di	=1N4258:20V	21	-	-
1N4270	Z-Di	=1N4258:22V	21	-	-
1N4271	Z-Di	=1N4258:24V	21	-	-
1N4272	Z-Di	=1N4258:27V	21	-	-
1N4273	Z-Di	=1N4258:30V	21	-	-
1N4274	Z-Di	=1N4258:33V	21	-	-
1N4275	Z-Di	=1N4258:36V	21	-	-
1N4276	Z-Di	=1N4258:39V	21	-	-
1N4277	Z-Di	=1N4258:43V	21	-	-
1N4278	Z-Di	=1N4258:47V	21	-	-
1N4279	Z-Di	=1N4258:51V	21	-	-
1N4280	Z-Di	=1N4258:56V	21	-	-
1N4281	Z-Di	=1N4258:62V	21	-	-
1N4282	Z-Di	=1N4258:68V	21	-	-
1N4283	Z-Di	=1N4258:75V	21	-	-
1N4284	Z-Di	=1N4258:82V	21	-	-
1N4285	Z-Di	=1N4258:91V	21	-	-
1N4286	Z-Di	=1N4258:100V	21	-	-
1N4287	Z-Di	=1N4258:110V	21	-	-
1N4288	Z-Di	=1N4258:120V	21	-	-

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1N4289	Z-Di	=1N4258:130V	21	-	-
1N429	Ref-Di	6,2V,5%,0,2W	2c	Inr,Mot,++	BZV10,BZV27,BZX90,1N821,1N4580,+
1N4290	Z-Di	=1N4258:150V	21	-	-
1N4291	Z-Di	=1N4258:160V	21	-	-
1N4292	Z-Di	=1N4258:180V	21	-	-
1N4293	Z-Di	=1N4258:200V	21	-	-
1N4294	Si-Di	UHF,S-Band-M,3060MHz	Koax	USA	-
1N4295(A)	Ref-Di	10V,0,4W	31a	USA	-
1N4296(A)	Ref-Di	10V,1W	34a	USA	-
1N4297(A,B)	Ref-Di	8,8V,5%,10W	32	USA	-
1N4298(A,B)	Ref-Di	8,8V,5%,10W	32	-	-
1N4299(A,B)	Ref-Di	11,3V,5%,10W	32	-	-
1N43	Ge-Di	Uni,70V,40mA	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54
1N430(A,B)	Ref-Di	8,4V,5%,0,25W	-	USA	-
1N4300(A,B)	Ref-Di	11,3V,5%,10W	32	-	-
1N4301(A,B)	Ref-Di	8,8V,5%,50W	32	-	-
1N4302(A,B)	Ref-Di	8,8V,5%,50W	32	-	-
1N4303(A,B)	Ref-Di	11,3V,5%,50W	32	-	-
1N4304(A,B)	Ref-Di	11,3V,5%,50W	32	-	-
1N4305	Si-Di	SS,75V,0,1A,<2pF(0V),<4ns	31a	USA,Hit,Tho	BAW62,BAW76,BAX95,1N4148..49,+
1N4306	Si-Di	2xSS,75V,0,2A,<2pF(0V),<4ns	42	USA	-
1N4307	Si-Di	4xSS,75V,0,2A,<2pF(0V),<4ns	-	USA	-
1N4308	Si-Di	SS,100V,<2pF(0V),<2ns	31a	USA,Tho	BAW62,BAW76,BAX95,1N4148..49,+
1N4309	Si-Di	SS,50V,<4pF(0V),<2ns	31a	USA,Tho	(BAW24..27)
1N431(B)	Si-Di	Uni,68V,10mA,B:75V	2c	USA	BA147/100,BA188,1N5194..96,+
1N4310	Si-Di	SS,75V,<4pF(0V),<2ns	31a	USA,Tho	(BAW26..27)
1N4311	Si-Di	SS,100V,<2pF(0V),<2ns	31a	USA,Tho	(BAW14)
1N4312	Si-Di	SS,150V,<2pF(0V),<2ns	31a	USA,Tho	(BAW14)
1N4313	Si-Di	SS,100V,<1pF(0V),<4ns	31a	USA,Tho	BAW62,BAW76,BAX95,1N4148..49,+
1N4314	Si-Di	=1N4308:Min	31a	-	→1N4308
1N4315	Si-Di	=1N4309:Min	31a	-	→1N4309
1N4316	Si-Di	=1N4310:Min	31a	-	→1N4310
1N4317	Si-Di	=1N4311:Min	31a	-	→1N4311
1N4318	Si-Di	=1N4312:Min	31a	-	→1N4312
1N4319	Si-Di	=1N4313:Min	31a	-	→1N4313
1N432(A,B)	Si-Di	SS,40V,SS(A:70,B:85)mA,3ns	-	USA	BA318,BAY38,BAX13,1N3062..64,+
1N4320	Si-Di	<1pF(0V)	-	USA	-
1N4321	Z-Di	50V,10%,3W	31a	USA	BZT03/CS1,BZV40/CS1,BZV48/CS1
1N4322	Si-Di	SS,75V,Uf<1,5pF(0V),<6ns	31a	USA	BAW62,BAW76,BAX95,1N4148..49,+
1N4323	Z-Di	6,8V,20%,1W	31a	USA	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1N4323A...4358A	Z-Di	=1N4323..4358:10%	31a	-	-
1N4323A..4358A	Z-Di	=1N4323..4358:10%	31a	-	-
1N4323B...4358B	Z-Di	=1N4323..4358:5%	31a	-	-
1N4323B..4358B	Z-Di	=1N4323..4358:5%	31a	-	-
1N4324	Z-Di	=1N4323:7,5V	31a	-	-
1N4325	Z-Di	=1N4323:8,2V	31a	-	-
1N4326	Z-Di	=1N4323:9,1V	31a	-	-
1N4327	Z-Di	=1N4323:10V	31a	-	-
1N4328	Z-Di	=1N4323:11V	31a	-	-
1N4329	Z-Di	=1N4323:12V	31a	-	-
1N433(A,B)	Si-Di	S,145V,40(A:50,B:60)mA,3ns	-	USA	BA203
1N4330	Z-Di	=1N4323:13V	31a	-	-
1N4331	Z-Di	=1N4323:15V	31a	-	-
1N4332	Z-Di	=1N4323:16V	31a	-	-
1N4333	Z-Di	=1N4323:18V	31a	-	-
1N4334	Z-Di	=1N4323:20V	31a	-	-
1N4335	Z-Di	=1N4323:22V	31a	-	-
1N4336	Z-Di	=1N4323:24V	31a	-	-
1N4337	Z-Di	=1N4323:27V	31a	-	-
1N4338	Z-Di	=1N4323:30V	31a	-	-
1N4339	Z-Di	=1N4323:33V	31a	-	-
1N434(A,B)	Si-Di	S,180V,35(A:45,B:60)mA,3ns	-	USA	-
1N4340	Z-Di	=1N4323:36V	31a	-	-
1N4341	Z-Di	=1N4323:39V	31a	-	-

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1N4342	Z-Di	=1N4323:43V	31a	-	-
1N4343	Z-Di	=1N4323:47V	31a	-	-
1N4344	Z-Di	=1N4323:51V	31a	-	-
1N4345	Z-Di	=1N4323:56V	31a	-	-
1N4346	Z-Di	=1N4323:62V	31a	-	-
1N4347	Z-Di	=1N4323:68V	31a	-	-
1N4348	Z-Di	=1N4323:75V	31a	-	-
1N4349	Z-Di	=1N4323:82V	31a	-	-
1N435	Ge-Di	4x Uni, 40V, 60mA	-	Spe	-
1N4350	Z-Di	=1N4323:91V	31a	-	-
1N4351	Z-Di	=1N4323:100V	31a	-	-
1N4352	Z-Di	=1N4323:110V	31a	-	-
1N4353	Z-Di	=1N4323:120V	31a	-	-
1N4354	Z-Di	=1N4323:130V	31a	-	-
1N4355	Z-Di	=1N4323:150V	31a	-	-
1N4356	Z-Di	=1N4323:160V	31a	-	-
1N4357	Z-Di	=1N4323:180V	31a	-	-
1N4358	Z-Di	=1N4323:200V	31a	-	-
1N4359	Si-Di	Rauschdiode, white noise diode, 200V	31a	Sol	-
1N436	Ref-Di	4V	-	Ray	-
1N4360	Z-Di	2,4V, 5%, 0,25W	31a	USA, Sie	BZX55/C2V4, BZX79/C2V4, 1N5221,+
1N4361	Si-Di	Gl, 900V, 0,5A	31a	USA	BY127, BY133, BY227, 1N4007,+
1N4362	Si-St	0,65V(1mA), 0,4W	31a	USA	BZ102/0V7, BZX55/C0V8, ZPD1
1N4363	Si-Di	S, 120V, 0,1A, <3pF(0V), <40ns	31a	USA	BA197..198, BAV19..21, 1N3070,+
1N4364	Si-Di	Gl, 100V, 0,75A	34a	USA, Tfk	BY126..127, BY133..135, 1N4002..07,+
1N4364R..4369R	Si-Di	=1N4364..4369:	34b	-	→1N4364..4369
1N4364R..4369R	Si-Di	-	34b	-	1N4364..4369
1N4365	Si-Di	=1N4364:200V	34a	-	BY126..127, BY133..134, 1N4003..07,+
1N4366	Si-Di	=1N4364:300V	34a	-	BY126..127, BY133..134, 1N4004..07,+
1N4367	Si-Di	=1N4364:400V	34a	-	BY126..127, BY133..134, 1N4004..07,+
1N4368	Si-Di	=1N4364:500V	34a	-	BY126..127, BY133..134, 1N4005..07,+
1N4369	Si-Di	=1N4364:600V	34a	-	BY126..127, BY133..134, 1N4005..07,+
1N437(A)	Ref-Di	5V	-	Ray	-
1N4370	Z-Di	2,4V, 10%, 0,4W	31a	USA, Sie, Tho	BZX55/.., BZX79/.., ZPD.., 1N5221..25
1N4370A	Z-Di	2.4V, 0.5W, Zzt=30Ω	-	Fairchild	-
1N4370A..4372A	Z-Di	=1N4370..4372:5%	31a	-	-
1N4370A..4372A	Z-Di	=1N4370..4372:5%	31a	-	-
1N4371	Z-Di	=1N4370:2,7V	31a	-	-
1N4371A	Z-Di	2.7V, 0.5W, Zzt=30Ω	-	Fairchild	-
1N4372	Z-Di	=1N4370:3V	31a	-	-
1N4372A	Z-Di	3V, 0.5W, Zzt=29Ω	-	Fairchild	-
1N4373	Si-Di	SS, 80V, 4ns	-		BAW62, BAW76, BAX95, 1N4148..49,+
1N4374	Si-Di	Gl, 1500V, 0,75A	34a	Scn	BY269, BY350/1500, DM513, GP10W,+
1N4375	Si-Di	SS, 60V, <2pF(0V), <6ns	31a	Idc, Spe	BA218, BAX13, BAX91, 1N4148..49,+
1N4376	Si-Di	SS, 10V, 0,05A, <1pF(0V), <6ns	31a	USA	BAY82, 1N4244
1N4377	Si-Di	kV-Gl, 2,5kV, 0,75A	-	Scn, Sem	-
1N4378	Opto	-	-	-	-
1N4379	Si-Di	UHF, S-Band-Dem, 3060MHz	31a	Miv, Sld	-
1N438(A)	Ref-Di	7V	-	Ray	-
1N4380	Si-Di	SS, 50V, 0,05A, <3pF(0V), <1,8ns	31a	USA	-
1N4381	Ge-Di	S, 25V, <1,2pF(0V), <100ns	31a	USA	AAY27, AAZ18, 1N3592
1N4382	Si-Di	SS, 55V, <2,5pF(0V), <5,5ns	31a	Msc	BAW76
1N4383(GP)	Si-Di	Gl, 200V, 1A	31a	USA, Gie, Tho	BY126..127, BY133..134, 1N4003..07,+
1N4384(GP)	Si-Di	=1N4383:400V	31a	-	BY126..127, BY133..134, 1N4004..07,+
1N4385(GP)	Si-Di	=1N4383:600V	31a	-	BY126..127, BY133..134, 1N4003..07,+
1N4386	Si-Di	UHF-Multiplier, 250V, PQ>32,5W(150MHz)	32a$	Pai	-
1N4387	Si-Di	UHF-Multiplier, 150V, PQ>15W(450MHz)	32a$	Mot, Pai	-
1N4388	Si-Di	UHF-Multiplier, 100V, PQ>11W(1000MHz)	32a$	Mot, Pai	-
1N4389	Si-Di	Uni, 5V	31a	Idc	-
1N439	Ref-Di	10V	-		-
1N4390	Si-Di	SS, 20V, <1pF(0V), <0,5ns	31a	USA	-
1N4391	Si-Di	SS, 20V, <1pF(0V), <0,5ns	31a	USA	-
1N4392	Si-Di	SS, 15V, <1pF(0V), <0,5ns	31a	USA	-
1N4393(A,B)	Si-Di	A: Ip/Ir>3,2, B: Ip/Ir>3,5	-		-

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1N4393(A,B)	Si-Di	Tunnel-Di, 0,25mA, Ip=0,1mA, Up<75mV	34	Msc, Ssi	-
1N4393(A,B)	Si-Di	Uv<475mV, Ip/Iv>2,5, <80pF, Rs<10e	-		-
1N4393A	Si-Di	-	34	Msc, Ssi	-
1N4393B	Si-Di	-	34	Msc, Ssi	-
1N4394(A,B)	Si-Di	Tunnel-Di, 0,5mA, Ip=0,22mA, Up<80mV	34	Msc, Ssi	-
1N4394(A,B)	Si-Di	Uv<480mV, Ip/Iv>2,5, <90pF, Rs<7e	-		-
1N4395(A,B)	Si-Di	Tunnel-Di, 1mA, Ip=0,47mA, Up<80mV	34	Msc, Ssi	-
1N4395(A,B)	Si-Di	Uv<490mV, Ip/Iv>2,5, <100pF, Rs<3e	-		-
1N4396(A,B)	Si-Di	Tunnel-Di, 2mA, Ip=1mA, Up<80mV	34	Msc, Ssi	-
1N4396(A,B)	Si-Di	Uv<500mV, Ip/Iv>2,5, <150pF, Rs<2e	-		-
1N4397(A,B)	Si-Di	Tunnel-Di, 4,5mA, Ip=2,2mA, Up<80mV	34	Msc, Ssi	-
1N4397(A,B)	Si-Di	Uv<510mV, Ip/Iv>2,5, <200pF, Rs<2e	-		-
1N4398(A,B)	Si-Di	Tunnel-Di, 10mA, Ip=4,6mA, Up<85mV	34	Msc, Ssi	-
1N4398(A,B)	Si-Di	Uv<520mV, Ip/Iv>2,5, <250pF, Rs<1e	-		-
1N4399(A,B)	Si-Di	Tunnel-Di, 15mA, Ip=10mA, Up<85mV	34	Msc, Ssi	-
1N4399(A,B)	Si-Di	Uv<530mV, Ip/Iv>2,5, <400pF, Rs<1e	-		-
1N44	Ge-Di	Uni, 115V, 35mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54
1N440(B)	Si-Di	Gl-L, 100V, 0,3A, B:0,75A	34a	Rca, Tix, ++	BY126..127, BY133..135, 1N4002..07, +
1N4400	Z-Di	6,8V, 20%, 1W	31a	USA	BZW22/.., BZX61/.., ZPY.., 1N5921..56, +
1N4400A...4435A	Z-Di	=1N4400..4435: 10%	31a	-	-
1N4400A..4435A	Z-Di	=1N4400..4435: 10%	31a	-	-
1N44008...4435B	Z-Di	=1N4400..4435: 5%	31a	-	-
1N44008..4435B	Z-Di	=1N4400..4435: 5%	31a	-	-
1N4401	Z-Di	=1N4400: 7,5V	31a	-	-
1N4402	Z-Di	=1N4400: 8,2V	31a	-	-
1N4403	Z-Di	=1N4400: 9,1V	31a	-	-
1N4404	Z-Di	=1N4400: 10V	31a	-	-
1N4405	Z-Di	=1N4400: 11V	31a	-	-
1N4406	Z-Di	=1N4400: 12V	31a	-	-
1N4407	Z-Di	=1N4400: 13V	31a	-	-
1N4408	Z-Di	=1N4400: 15V	31a	-	-
1N4409	Z-Di	=1N4400: 16V	31a	-	-
1N441(B)	Si-Di	=1N440(B): 200V	34a	-	BY126..127, BY133..134, 1N4003..07, +
1N4410	Z-Di	=1N4400: 18V	31a	-	-
1N4411	Z-Di	=1N4400: 20V	31a	-	-
1N4412	Z-Di	=1N4400: 22V	31a	-	-
1N4413	Z-Di	=1N4400: 24V	31a	-	-
1N4414	Z-Di	=1N4400: 27V	31a	-	-
1N4415	Z-Di	=1N4400: 30V	31a	-	-
1N4416	Z-Di	=1N4400: 33V	31a	-	-
1N4417	Z-Di	=1N4400: 36V	31a	-	-
1N4418	Z-Di	=1N4400: 39V	31a	-	-
1N4419	Z-Di	=1N4400: 43V	31a	-	-
1N442(B)	Si-Di	=1N440(B): 300V	34a	-	BY126..127, BY133..134, 1N4004..07, +
1N4420	Z-Di	=1N4400: 47V	31a	-	-
1N4421	Z-Di	=1N4400: 51V	31a	-	-
1N4422	Z-Di	=1N4400: 56V	31a	-	-
1N4423	Z-Di	=1N4400: 62V	31a	-	-
1N4424	Z-Di	=1N4400: 68V	31a	-	-
1N4425	Z-Di	=1N4400: 75V	31a	-	-
1N4426	Z-Di	=1N4400: 82V	31a	-	-
1N4427	Z-Di	=1N4400: 91V	31a	-	-
1N4428	Z-Di	=1N4400: 100V	31a	-	-
1N4429	Z-Di	=1N4400: 110V	31a	-	-
1N443(B)	Si-Di	=1N440(B): 400V	34a	-	BY126..127, BY133..134, 1N4004..07, +
1N4430	Z-Di	=1N4400: 120V	31a	-	-
1N4431	Z-Di	=1N4400: 130V	31a	-	-
1N4432	Z-Di	=1N4400: 150V	31a	-	-
1N4433	Z-Di	=1N4400: 160V	31a	-	-
1N4434	Z-Di	=1N4400: 180V	31a	-	-
1N4435	Z-Di	=1N4400: 200V	31a	-	-
1N4436	Si-Di	Gl-L, 200V, 10A	-	old	-
1N4437	Si-Di	=1N4436: 400V	-		-
1N4438	Si-Di	=1N4436: 600V	-		-

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1N4439	Si-Di	=1N4436: 800V	-		-
1N444(B)	Si-Di	=1N440(B): 500V, B: 0,65A	34a	-	BY126..127, BY133..134, 1N4005..07, +
1N4440	Si-Di	=1N4436: 1000V	-		-
1N4441	Si-Di	Gl, S, 1500V, 25mA, <300ns	31a	old	BY203/16, BY269, SHG1,5
1N4442	Si-Di	SS, 30V, 1ns	31a	-	BA218, BAX13, BAX91, 1N4148..49, +
1N4443	Si-Di	SS, 30V, 0,6ns	-		BA218, BAX13, BAX91, 1N4148..49, +
1N4444	Si-Di	SS, 70V, 0,225A, <2pF(0V), <7ns	31a	USA, Tix, Tho	BAW62, BAW76, BAX95, 1N4148..49, +
1N4445	Si-Di	SS, 125V, <1pF(0V), <4ns	31a	USA, Tho	BA219, BAX96
1N4446	Si-Di	SS, 100V, 0,2A, <pF(0V), <4ns	31a	USA, EUR	BAW62, BAX95, 1N4148..49, 1N4151, +
1N4447	Si-Di	SS, 100V, 0,2A, <2pF(0V), <4ns	31a	-	BAW62, BAX95, 1N4148..49, 1N4151, +
1N4448	Si-Di	SS, 100V, 0,2A, <4pF(0V), <4ns	31a	-	BAW62, BAX95, 1N4148..49, 1N4151, +
1N4448W	Si-Di	=1N4448: SMD	71a(2,7mm)	Gsi	MMSD914
1N4449	Si-Di	SS, 100V, 0,2A, <2pF(0V), <4ns	31a	-	BAW62, BAX95, 1N4148..49, 1N4151, +
1N445(B)	Si-Di	=1N440(B): 600V, B: 0,65A	34a	-	BY126..127, BY133..134, 1N4005..07, +
1N4450	Si-Di	SS, 30V, 0,2A, <4pF(0V), <4ns	31a	USA, EUR, Mit	BA221, BAY74, 1N4148..49, 1N4154, +
1N4451	Si-Di	SS, 30V, 0,2A, <6pF(0V), <10ns	31a	USA, EUR	BA221, BAY74, 1N4148..49, 1N4154, +
1N4452	Si-Di	S, 40V, <30pF(0V), <20ns	31a	USA	BAV15..16, BAV44, BAW24..27
1N4453	Si-St	0,8V(10mA), 0,5W	31a	USA	BA220, BZ102/0V7, BZX55/C0V8, ZPD1, +
1N4454	Si-Di	SS, 50V, 0,2A, <2pF(0V), <10ns	31a	USA, EUR, Mit	BAW62, BAX95, 1N4148..49, 1N4151, +
1N4455	Si-Di	Uni, 50V	31a	Gen, Tix, Uni	BA128, BA147/50, BA222, 1N5194, +
1N4456	Si-Di	SS, 35V, <1,5pF(0V), <1,5ns	31a	Idc, Sem	-
1N4457	Si-Di	SS, 50V, <1,1pF(0V), <1,5ns	31a	Idc, Sem	-
1N4458	Si-Di	Gl-L, 800V, 5A(Tc=150o)	32a$	USA	BYX38/900, BYX39/800
1N4458R..4459R	Si-Di	=1N4458..4459:	32b&	-	BYX38/..R, BYX39/..R
1N4458R..4459R	Si-Di	-	32b&	-	BYX38/..R, BYX39/..R
1N4459	Si-Di	=1N4458: 1000V	32a$	-	BYX38/1200, BYX39/1000
1N446	Si-Di	UHF, K/Ka-Band-Dem, 34,8GHz	Koax	Syl	-
1N4460	Z-Di	6,2V, 5%, 1,5W	31a	USA	BZV47/.., BZY97/.., ZY.., 1N5920..56, +
1N4461	Z-Di	=1N4460: 6,8V	31a	-	-
1N4462	Z-Di	=1N4460: 7,5V	31a	-	-
1N4463	Z-Di	=1N4460: 8,2V	31a	-	-
1N4464	Z-Di	=1N4460: 9,1V	31a	-	-
1N4465	Z-Di	=1N4460: 10V	31a	-	-
1N4466	Z-Di	=1N4460: 11V	31a	-	-
1N4467	Z-Di	=1N4460: 12V	31a	-	-
1N4468	Z-Di	=1N4460: 13V	31a	-	-
1N4469	Z-Di	=1N4460: 15V	31a	-	-
1N447	Ge-Di	Uni, 40V, 60mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, +
1N4470	Z-Di	=1N4460: 16V	31a	-	-
1N4471	Z-Di	=1N4460: 18V	31a	-	-
1N4472	Z-Di	=1N4460: 20V	31a	-	-
1N4473	Z-Di	=1N4460: 22V	31a	-	-
1N4474	Z-Di	=1N4460: 24V	31a	-	-
1N4475	Z-Di	=1N4460: 27V	31a	-	-
1N4476	Z-Di	=1N4460: 30V	31a	-	-
1N4477	Z-Di	=1N4460: 33V	31a	-	-
1N4478	Z-Di	=1N4460: 36V	31a	-	-
1N4479	Z-Di	=1N4460: 39V	31a	-	-
1N448	Ge-Di	Uni, 100V, 60mA, 0,5pF(3V)	31a	USA	AA117..118, AA132..133
1N4480	Z-Di	=1N4460: 43V	31a	-	-
1N4481	Z-Di	=1N4460: 47V	31a	-	-
1N4482	Z-Di	=1N4460: 51V	31a	-	-
1N4483	Z-Di	=1N4460: 56V	31a	-	-
1N4484	Z-Di	=1N4460: 62V	31a	-	-
1N4485	Z-Di	=1N4460: 68V	31a	-	-
1N4486	Z-Di	=1N4460: 75V	31a	-	-
1N4487	Z-Di	=1N4460: 82V	31a	-	-
1N4488	Z-Di	=1N4460: 91V	31a	-	-
1N4489	Z-Di	=1N4460: 100V	31a	-	-
1N449	Ge-Di	Uni, 40V, 60mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, +
1N4490	Z-Di	=1N4460: 110V	31a	-	-
1N4491	Z-Di	=1N4460: 120V	31a	-	-
1N4492	Z-Di	=1N4460: 130V	31a	-	-
1N4493	Z-Di	=1N4460: 150V	31a	-	-

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1N4494	Z-Di	=1N4460:160V	31a	-	-
1N4495	Z-Di	=1N4460:180V	31a	-	-
1N4496	Z-Di	=1N4460:200V	31a	-	-
1N4497	Si-Di	kV-Gl,1,6kV,0,75A	-	Sem,Ssi	-
1N4498	Si-Di	=1N4497:3kV	-		-
1N4499	Z-Di	6,2V,5%,1W	31a	Idc,Sem	BZW22/C6V2,BZX61/C6V2,ZPY6,2,1N5920+
1N44A1	Si-Di	kV-Gl,13kV,0,67A	-	Tos	-
1N45	Ge-Di	HF,Uni,75V,35mA	31a	USA	AA113,AA117..118,1N34,1N60
1N450	Ge-Di	Uni,100V,60mA	31a	USA	AA117..118,AA132..133
1N4500	Si-Di	SS,80V,<4pF(0V),<4ns	31a	USA	BAW62,BAX95,1N4148..49,1N4151,+
1N4501	Ref-Di	7V,5%,0,21W	31a	Idc,Msc	-
1N4502	Ge-Di	Uni,20V	31a	Idc,Sem	AA117..119,AA132..134,1N34,1N54,+
1N4503	Z-Di	33V,10%,3W	31a	Msc,Trw	BZT03/C,D33
1N4504	Z-Di	200V,10%,3W	31a	Msc,Trw	BZT03/C,D200
1N4505	Si-Di	kV-Gl,6kV,0,1A	31a	USA	BYX90,1N5183
1N4506	Si-Di	Gl,contr.av.,200V,12A(Tc=135o)	32a$	USA	BYX25/600
1N4507	Si-Di	=1N4506:400V	32a$	-	BYX25/600
1N4508	Si-Di	=1N4506:600V	32a$	-	BYX25/600
1N4509	Si-Di	=1N4506:800V	32a$	-	BYX25/800
1N451	Ge-Di	Uni,175V,60mA	31a	USA	1N38
1N4510	Si-Di	=1N4506:1000V	32a$	-	BYX25/1000
1N4511	Si-Di	=1N4506:1200V	32a$	-	BYX25/1200
1N4512	Si-Di	Uni,10V	12a	Ssi	BA128,BA147/25,BA222,1N5194,+
1N4513	Si-Di	Gl,2000V,0,25A	31a	USA	BAY91,BY203/20,HVG2,SHG2,+
1N4514	Si-Di	Gl,800V,1,1A	91a	USA	BY127,BY133,BY227,1N4006..07,+
1N4517	Si-Di	Gl,200V,2A	31a	USA	BY251..255,BY259/300,1N5060..62,+
1N452	Ge-Di	Uni,35V	31a	USA	AA136
1N4523	Ge-Di	SS,15V,<1,5pF(0V),<8ns	31a	USA	AAY21
1N4524	Ge-Di	SS,10V,<2pF(0V),<3ns	31a	USA	1N995
1N4525	Si-Di	Gl-L,contr.av.,200V,35A(Tc=115o)	32a$	USA	BYX56/600
1N4526	Si-Di	=1N4525:400V	32a$	-	BYX56/600
1N4527	Si-Di	=1N4525:600V	32a$	-	BYX56/600
1N4528	Si-Di	=1N4525:800V	32a$	-	BYX56/800
1N4529	Si-Di	=1N4525:1000V	32a$	-	BYX56/1000
1N453	Ge-Di	Uni,115V	31a	USA	1N270
1N4530	Si-Di	=1N4525:1200V	32a$	-	BYX56/1200
1N4531	Si-Di	SS,75V,0,15A,<4pF(0V),<4ns	31a	USA,Phi,Tho	BAW62,BAX95,1N4148..49,1N4151,+
1N4532	Si-Di	SS,75V,0,15A,<2pF(0V),<2ns	31a	USA,Phi,Tho	BAW62,BAX95,1N4148..49,1N4151,+
1N4533	Si-Di	SS,40V,0,075A,<2pF(0V),<2ns	31a	USA,Phi,Tho	BAW62,BAX95,1N4148..49,1N4151,+
1N4534	Si-Di	SS,75V,0,075A,<2pF(0V),<2ns	31a	USA,Phi,Tho	BAW62,BAX95,1N4148..49,1N4151,+
1N4535	Z-Di	bidirektional,3,45V,5%,0,5W	31a	USA,Sie	-
1N4536	Si-Di	SS,25V,0,075A,<4pF(0V),<2ns	31a	USA,Hit	BA218,BAX13,BAX91,1N4148..49,+
1N4537	Si-Di	Gl-L,1800V,3A(Tc=100o)	32a$	USA	-
1N4538	Si-Di	=1N4537:2400V	32a$	-	-
1N4539	Si-Di	=1N4537:3000V	32a$	-	-
1N454	Ge-Di	Uni,60V	31a	USA	AA136,1N270
1N4540	Si-Di	=1N4537:3600V	32a$	-	-
1N4541	Si-Di	Gl,225V,0,4A	31a	Sem,Trw	BA157..159,BY204/4,BY206..207,+
1N4542	Si-Di	=1N4541:400V	31a	-	BA157..199,BY204/4,BY207,+
1N4543	Si-Di	=1N4541:600V	31a	-	BA158..159,BY204/8,BY207,+
1N4544	Si-Di	=1N4541:800V	31a	-	BA159,BY204/8,BY208/800,+
1N4545	Si-Di	=1N4541:1000V	31a	-	BA159,BY204/10,BY208/1000,+
1N4546	Si-Di	kV-Gl,25kV,1A	-	Sem	-
1N4547	Si-Di	HF/S,25V,<1,2pF(0V),<60ns	-	Idc,Sem	-
1N4548	Si-Di	Min,SS,25V,<4pF(0V),<2ns	31a	Idc,Sem	(BA217,BA317,BAY71,1N4148..49,++)
1N4549	Z-Di	3,9V,20%,50W(Tc=75o)	32b&	USA,Mot,Sie	-
1N4549A..4556A	Z-Di	=1N4549..4556:10%	32b&	-	-
1N4549A..4556A	Z-Di	=1N4549..4556:10%	32b&	-	-
1N4549B..4556B	Z-Di	=1N4549..4556:5%	32b&	-	-
1N4549B..4556B	Z-Di	=1N4549..4556:5%	32b&	-	-
1N4549R..4556R	Z-Di	=1N4549..4556:	32a$	-	-
1N4549R..4556R	Z-Di	=1N4549..4556:	32a$	-	-
1N455	Ge-Di	Uni,35V	31a	USA	AA136,AA139,1N270
1N4550	Z-Di	=1N4549:4,3V	32b&	-	-

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1N4551	Z-Di	=1N4549:4,7V	32b&	-	-
1N4552	Z-Di	=1N4549:5,1V	32b&	-	-
1N4553	Z-Di	=1N4549:5,6V	32b&	-	-
1N4554	Z-Di	=1N4549:6,2V	32b&	-	-
1N4555	Z-Di	=1N4549:6,8V	32b&	-	-
1N4556	Z-Di	=1N4549:7,5V	32b&	-	-
1N4557	Z-Di	3,9V,20%,50W(Tc=75o)	23d1&	USA,Mot,Sie	-
1N4557A...4564A	Z-Di	=1N4557..4564:10%	23d1&	-	-
1N4557A..4564AR	Z-Di	=1N4557..4564:10%	23d1&	-	-
1N4557B...4564B	Z-Di	=1N4557..4564:5%	23d1&	-	-
1N4557B..4564BR	Z-Di	=1N4557..4564:5%	23d1&	-	-
1N4557R...4564R	Z-Di	=1N4557..4564:	23c1$	-	-
1N4557R..4564RR	Z-Di	=1N4557..4564:	23c1$	-	-
1N4558	Z-Di	=1N4557:4,3V	23d1&	-	-
1N4559	Z-Di	=1N4557:4,7V	23d1&	-	-
1N456(A)	Si-Di	Uni,35V,0,09A,A:0,2A	31a	Fch,Ttx,++	BA127,BA187..190,BA215,1N484A,+
1N4560	Z-Di	=1N4557:5,1V	23d1&	-	-
1N4561	Z-Di	=1N4557:5,6V	23d1&	-	-
1N4562	Z-Di	=1N4557:6,2V	23d1&	-	-
1N4563	Z-Di	=1N4557:6,8V	23d1&	-	-
1N4564	Z-Di	=1N4557:7,5V	23d1&	-	-
1N4565(A,B)	Ref-Di	6,4V,5%,0,4W	31a	USA,Sie,Tho	BZV10,BZV27,BZX90
1N4566(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	BZV11,BZV28,BZX91
1N4567(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	BZV12,BZV29,BZX92
1N4568(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	BZV13,BZV30,BZX93
1N4569(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	BZV14,BZV31,BZX94
1N457(A)	Si-Di	Uni,75V,0,075A,A:0,2A	31a	Fch,Ttx,++	BA188..190,BAY45,BAY73,1N484A,+
1N4570(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4571(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4572(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4573(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4574(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4575(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4576(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4577(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4578(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4579(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N458(A)	Si-Di	Uni,150V,0,055A,A:0,2A	31a	Fch,Ttx,++	BA189..190,BAY45,BAW52,1N484A,+
1N4580(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4581(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4582(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4583(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4584(A,B)	Ref-Di	6,4V,5%,0,4W	31a	-	-
1N4585(GP)	Si-Di	Gl,800V,1A	31a	USA,Gle,Tho	BY127,BY133,BY227,1N4006..07,+
1N4586(GP)	Si-Di	=1N4585:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N4587	Si-Di	Gl-L,100V,150A(Tc=110o)	73a$	USA	-
1N4587R...4596R	Si-Di	=1N4587..4596:	73b&	-	-
1N4587R..4596R	Si-Di	-	73b&	-	-
1N4588	Si-Di	=1N4587:200V	73a$	-	-
1N4589	Si-Di	=1N4587:300V	73a$	-	-
1N459(A)	Si-Di	Uni,200V,0,04A,A:0,2A	31a	Fch,Ttx,++	BA190,BAY46,BAW52,BAY20..21,+
1N4590	Si-Di	=1N4587:400V	73a$	-	-
1N4591	Si-Di	=1N4587:500V	73a$	-	-
1N4592	Si-Di	=1N4587:600V	73a$	-	-
1N4593	Si-Di	=1N4587:800V	73a$	-	-
1N4594	Si-Di	=1N4587:1000V	73a$	-	-
1N4595	Si-Di	=1N4587:1200V	73a$	-	-
1N4596	Si-Di	=1N4587:1400V	73a$	-	-
1N4598(A)	Si-Di	VHF-Tuning,90V,22pF(4V)	31a	Tdy	-
1N4599(A)	Si-Di	VHF-Tuning,110V,47pF(4V)	31a	Tdy	-
1N46	Ge-Di	Uni,60V,40mA	31a	USA	AA117..118,AA132..134,1N34,1N54
1N460(A,B)	Si-Di	Uni,S,90V,45mA,A:60mA,B:70mA	-	USA	BA147/100,BA189..190,1N5195..96,+
1N4600	Si-Di	UHF,M-Band-Mi,10..16GHz	Koax	Mlv,Sid	-
1N4601	Si-Di	UHF,M-Band-Mi,10..16GHz	Koax	Mlv,Sid	-

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1N4602	Si-Di	UHF, M-Band-M, 10..16GHz	Koax	USA	-
1N4603	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	-
1N4604	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	-
1N4605	Si-Di	UHF, Ku-Band-M, 12,5..17,5GHz	Koax	USA	-
1N4606	Si-Di	SS, 85V, 0,35A, <2,5pF(0V), <6ns	31a	USA, Tlx	BAV10, BAW55, BAW76, BAX83
1N4607	Si-Di	SS, 85V, 0,35A, <4pF(0V), <15ns	31a	USA, Tlx	BAV10, BAW55, BAW76, BAX83
1N4608	Si-Di	SS, 85V, 0,35A, <4pF(4V), <15ns	31a	USA, Tlx	BAV10, BAW55, BAW76, BAX83
1N4609(A)	Si-Di	VHF-Tuning, 35V, 22pF(4V)	31a	Idc, Msc	-
1N461(A)	Si-Di	Uni, 30V, 0,06A, A:0,2A	31a	Fch, Tlx, ++	BA127, BA187..190, BA215, 1N484A, +
1N4610	Si-Di	SS, 80V, <2pF(0V), <4ns	31a	USA	BAW62, BAW76, BAX95, 1N4148..49, +
1N4611(A,B,C)	Ref-Di	6,6V, 5%, 0,25W	31a	USA	BZV11..14, BZV28..31, 1N4575..84, +
1N4612(A,B,C)	Ref-Di	6,6V, 5%, 0,25W	31a	-	-
1N4613(A,B,C)	Ref-Di	6,6V, 5%, 0,25W	31a	-	-
1N4614	Z-Di	ra, 1,8V, 5%, 0,25W	31a	USA, Sie, Tho	-
1N4615	Z-Di	=1N4614: 2V	31a	-	-
1N4616	Z-Di	=1N4614: 2,2V	31a	-	-
1N4617	Z-Di	=1N4614: 2,4V	31a	-	-
1N4618	Z-Di	=1N4614: 2,7V	31a	-	-
1N4619	Z-Di	=1N4614: 3V	31a	-	-
1N462(A)	Si-Di	Uni, 70V, 0,05A, A:0,2A	31a	Fch, Tlx, ++	BA127, BA188..190, BA215, 1N484A, +
1N4620	Z-Di	=1N4614: 3,3V	31a	-	-
1N4621	Z-Di	=1N4614: 3,6V	31a	-	-
1N4622	Z-Di	=1N4614: 3,9V	31a	-	-
1N4623	Z-Di	=1N4614: 4,3V	31a	-	-
1N4624	Z-Di	=1N4614: 4,7V	31a	-	-
1N4625	Z-Di	=1N4614: 5,1V	31a	-	-
1N4626	Z-Di	=1N4614: 5,6V	31a	-	-
1N4627	Z-Di	=1N4614: 6,2V	31a	-	-
1N4628	Z-Di	6,8V, 5%, 0,6W	31a	USA, Sie	BZX55/.., BZX83/.., ZPD.., 1N5235..61, +
1N4629	Z-Di	=1N4628: 7,5V	31a	-	-
1N463(A)	Si-Di	Uni, 200V, 0,03A, A:0,2A	31a	Fch, Tlx, ++	BA190, BAW52, BAY46, BAY21, +
1N4630	Z-Di	=1N4628: 8,2V	31a	-	-
1N4631	Z-Di	=1N4628: 9,1V	31a	-	-
1N4632	Z-Di	=1N4628: 10V	31a	-	-
1N4633	Z-Di	=1N4628: 11V	31a	-	-
1N4634	Z-Di	=1N4628: 12V	31a	-	-
1N4635	Z-Di	=1N4628: 13V	31a	-	-
1N4636	Z-Di	=1N4628: 15V	31a	-	-
1N4637	Z-Di	=1N4628: 16V	31a	-	-
1N4638	Z-Di	=1N4628: 18V	31a	-	-
1N4639	Z-Di	=1N4628: 20V	31a	-	-
1N464(A)	Si-Di	Uni, 150V, 0,04A, A:0,2A	31a	Fch, Tlx, ++	BA189..190, BAW52, BAY45, 1N484A, +
1N4640	Z-Di	=1N4628: 22V	31a	-	-
1N4641	Z-Di	=1N4628: 24V	31a	-	-
1N4642	Z-Di	=1N4628: 27V	31a	-	-
1N4643	Z-Di	=1N4628: 30V	31a	-	-
1N4644	Z-Di	=1N4628: 33V	31a	-	-
1N4645	Z-Di	=1N4628: 36V	31a	-	-
1N4646	Z-Di	=1N4628: 39V	31a	-	-
1N4647	Z-Di	=1N4628: 43V	31a	-	-
1N4648	Z-Di	=1N4628: 47V	31a	-	-
1N4649	Z-Di	3,3V, 5%, 1W	31a	USA	BZW22/.., BZX61/.., ZPY.., 1N5913..41, +
1N465	Z-Di	2,6V, 10%, 0,25W	2c	USA	BZX55/.., BZX79/.., ZPD.., 1N5221..36, +
1N4650	Z-Di	=1N4649: 3,6V	31a	-	-
1N4651	Z-Di	=1N4649: 3,9V	31a	-	-
1N4652	Z-Di	=1N4649: 4,3V	31a	-	-
1N4653	Z-Di	=1N4649: 4,7V	31a	-	-
1N4654	Z-Di	=1N4649: 5,1V	31a	-	-
1N4655	Z-Di	=1N4649: 5,6V	31a	-	-
1N4656	Z-Di	=1N4649: 6,2V	31a	-	-
1N4657	Z-Di	=1N4649: 6,8V	31a	-	-
1N4658	Z-Di	=1N4649: 7,5V	31a	-	-
1N4659	Z-Di	=1N4649: 8,2V	31a	-	-
1N465A..470A	Z-Di	=1N465..470: 5%	2c	-	-

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1N465A..470A	Z-Di	=1N465..470:5%	2c	-	-
1N465B...470B	Z-Di	=1N465..470:1%	2c	-	-
1N465B..470B	Z-Di	=1N465..470:1%	2c	-	-
1N466	Z-Di	=1N465:3,5V	2c	-	-
1N4660	Z-Di	=1N4649:9,1V	31a	-	-
1N4661	Z-Di	=1N4649:10V	31a	-	-
1N4662	Z-Di	=1N4649:11V	31a	-	-
1N4663	Z-Di	=1N4649:12V	31a	-	-
1N4664	Z-Di	=1N4649:13V	31a	-	-
1N4665	Z-Di	=1N4649:15V	31a	-	-
1N4666	Z-Di	=1N4649:16V	31a	-	-
1N4667	Z-Di	=1N4649:18V	31a	-	-
1N4668	Z-Di	=1N4649:20V	31a	-	-
1N4669	Z-Di	=1N4649:22V	31a	-	-
1N467	Z-Di	=1N465:4,1V	2c	-	-
1N4670	Z-Di	=1N4649:24V	31a	-	-
1N4671	Z-Di	=1N4649:27V	31a	-	-
1N4672	Z-Di	=1N4649:30V	31a	-	-
1N4673	Z-Di	=1N4649:33V	31a	-	-
1N4674	Z-Di	=1N4649:36V	31a	-	-
1N4675	Z-Di	=1N4649:39V	31a	-	-
1N4676	Z-Di	=1N4649:43V	31a	-	-
1N4677	Z-Di	=1N4649:47V	31a	-	-
1N4678	Z-Di	1,8V,5%,0,25W	31a	USA,Mot,Sie	BZX79/..,BZX55/..,ZPD..,1N5221..60,+
1N4679	Z-Di	=1N4678:2V	31a	-	-
1N468	Z-Di	=1N465:4,85V	2c	-	-
1N4680	Z-Di	=1N4678:2,2V	31a	-	-
1N4681	Z-Di	=1N4678:2,4V	31a	-	-
1N4682	Z-Di	=1N4678:2,7V	31a	-	-
1N4683	Z-Di	=1N4678:3V	31a	-	-
1N4684	Z-Di	=1N4678:3,3V	31a	-	-
1N4685	Z-Di	=1N4678:3,6V	31a	-	-
1N4686	Z-Di	=1N4678:3,9V	31a	-	-
1N4687	Z-Di	=1N4678:4,3V	31a	-	-
1N4688	Z-Di	=1N4678:4,7V	31a	-	-
1N4689	Z-Di	=1N4678:5,1V	31a	-	-
1N469	Z-Di	=1N465:5,8V	2c	-	-
1N4690	Z-Di	=1N4678:5,6V	31a	-	-
1N4691	Z-Di	=1N4678:6,2V	31a	-	-
1N4692	Z-Di	=1N4678:6,8V	31a	-	-
1N4693	Z-Di	=1N4678:7,5V	31a	-	-
1N4694	Z-Di	=1N4678:8,2V	31a	-	-
1N4695	Z-Di	=1N4678:8,7V	31a	-	-
1N4696	Z-Di	=1N4678:9,1V	31a	-	-
1N4697	Z-Di	=1N4678:10V	31a	-	-
1N4698	Z-Di	=1N4678:11V	31a	-	-
1N4699	Z-Di	=1N4678:12V	31a	-	-
1N47	Ge-Di	Uni,150V,30mA	31a	USA	AA133,1N39
1N470	Z-Di	=1N465:7,1V	2c	-	-
1N4700	Z-Di	=1N4678:13V	31a	-	-
1N4701	Z-Di	=1N4678:14V	31a	-	-
1N4702	Z-Di	=1N4678:15V	31a	-	-
1N4703	Z-Di	=1N4678:16V	31a	-	-
1N4704	Z-Di	=1N4678:17V	31a	-	-
1N4705	Z-Di	=1N4678:18V	31a	-	-
1N4706	Z-Di	=1N4678:19V	31a	-	-
1N4707	Z-Di	=1N4678:20V	31a	-	-
1N4708	Z-Di	=1N4678:22V	31a	-	-
1N4709	Z-Di	=1N4678:24V	31a	-	-
1N471	Z-Di	3,5V,10%,0,2W	2c	USA	BZX55/..,BZX79/..,ZPD..,1N5221..36,+
1N4710	Z-Di	=1N4678:25V	31a	-	-
1N4711	Z-Di	=1N4678:27V	31a	-	-
1N4712	Z-Di	=1N4678:28V	31a	-	-
1N4713	Z-Di	=1N4678:30V	31a	-	-

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1N4714	Z-Di	=1N4678:33V	31a	-	-
1N4715	Z-Di	=1N4678:36V	31a	-	-
1N4716	Z-Di	=1N4678:39V	31a	-	-
1N4717	Z-Di	=1N4678:43V	31a	-	-
1N4718	Si-Di	S,50V,<8pF(0V),<180ns	31a	USA	BYT52A,BYX92/50,MR810,RGP10A,+
1N4719	Si-Di	GI,50V,3A(Tc=75o)	34a	USA,Mot	BY396..399,RGP30A,(BY205/100,++)
1N4719R...4725R	Si-Di	=1N4719..4725:	34b	-	→1N4719..4725
1N4719R..4725R	Si-Di	-	34b	-	1N4719..4725
1N471A...475A	Z-Di	=1N471..475:5%	2c	-	-
1N471A..475A	Z-Di	=1N471..475:5%	2c	-	-
1N471B...475B	Z-Di	=1N471..475:1%	2c	-	-
1N471B..475B	Z-Di	=1N471..475:1%	2c	-	-
1N472	Z-Di	=1N471:4,1V	2c	-	-
1N4720	Si-Di	=1N4719:100V	34a	-	BY396..399,RGP30B,(BY205/100,++)
1N4721	Si-Di	=1N4719:200V	34a	-	BY397..399,RGP30D,(BY205/200,++)
1N4722	Si-Di	=1N4719:400V	34a	-	BY398..399,RGP30G,(BY205/400,++)
1N4723	Si-Di	=1N4719:600V	34a	-	BY228,BY399,RPG30J,(BY205/600,++)
1N4724	Si-Di	=1N4719:800V	34a	-	BY228,BY399,RGP30K,(BY205/800,++)
1N4725	Si-Di	=1N4719:1000V	34a	-	BY228,BY438,RGP30M,(BY206/1000,++)
1N4726	Si-Di	SS,20V,0,06A,<4pF(0V)	31a	USA,Tlx,++	-
1N4727	Si-Di	SS,20V,0,075A,<4pF(0V)	31a	USA,Tlx	-
1N4728	Z-Di	3,3V,10%,1W	31a	USA,EUR,NR	BZW22/..,BZX61/..,ZPY..,1N5913..49,+
1N4728A	Z-Di	3.3V,1W,Zzt=0.1Ω	-	Fch	-
1N4728A...4764A	Z-Di	=1N4728..4764:5%	31a	-	-
1N4728A..4764A	Z-Di	=1N4728..4764:5%	31a	-	-
1N4729	Z-Di	=1N4728:3,6V	31a	-	-
1N4729A	Z-Di	3.6V,1W,Zzt=0.1Ω	-	Fch	-
1N473	Z-Di	=1N471:4,85V	2c	-	-
1N4730	Z-Di	=1N4728:3,9V	31a	-	-
1N4730A	Z-Di	3.9V,1W,Zzt=9Ω	-	Fch	-
1N4731	Z-Di	=1N4728:4,3V	31a	-	-
1N4731A	Z-Di	4.3V,1W,Zzt=9Ω	-	Fch	-
1N4732	Z-Di	=1N3728:4,7V	31a	-	-
1N4732A	Z-Di	4.7V,1W,Zzt=8Ω	-	Fch	-
1N4733	Z-Di	=1N4728:5,1V	31a	-	-
1N4733A	Z-Di	5.1V,1W,Zzt=7Ω	-	Fch	-
1N4734	Z-Di	=1N4728:5,6V	31a	-	-
1N4734A	Z-Di	5.6V,1W,Zzt=5Ω	-	Fch	-
1N4735	Z-Di	=1N4728:6,2V	31a	-	-
1N4735A	Z-Di	6.2V,1W,Zzt=2Ω	-	Fch	-
1N4736	Z-Di	=1N4728:6,8V	31a	-	-
1N4736A	Z-Di	6.8V,1W,Zzt=3.5Ω	-	Fch	-
1N4737	Z-Di	=1N4728:7,5V	31a	-	-
1N4737A	Z-Di	7.5V,1W,Zzt=4Ω	-	Fch	-
1N4738	Z-Di	=1N4728:8,2V	31a	-	-
1N4738A	Z-Di	8.2V,1W,Zzt=4.5Ω	-	Fch	-
1N4739	Z-Di	=1N4728:9,1V	31a	-	-
1N4739A	Z-Di	9.1V,1W,Zzt=5Ω	-	Fch	-
1N474	Z-Di	=1N471:5,8V	2c	-	-
1N4740	Z-Di	=1N4728:10V	31a	-	-
1N4740A	Z-Di	10V,1W	-	Fch	-
1N4741	Z-Di	=1N4728:11V	31a	-	-
1N4741A	Z-Di	11V,1W	-	Fch	-
1N4742	Z-Di	=1N4728:12V	31a	-	-
1N4742A	Z-Di	12V,1W,Zzt=9Ω	-	Fch	-
1N4743	Z-Di	=1N4728:13V	31a	-	-
1N4743A	Z-Di	13V,1W,Zzt=10Ω	-	Fch	-
1N4744	Z-Di	=1N4728:15V	31a	-	-
1N4744A	Z-Di	15V,1W,Zzt=14Ω	-	Fch	-
1N4745	Z-Di	=1N4728:16V	31a	-	-
1N4745A	Z-Di	16V,1W,Zzt=16Ω	-	Fch	-
1N4746	Z-Di	=1N4728:18V	31a	-	-
1N4746A	Z-Di	18V,1W,Zzt=20Ω	-	Fch	-
1N4747	Z-Di	=1N4728:20V	31a	-	-

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1N4747A	Z-Di	20V,1W	-	Fch	-
1N4748	Z-Di	=1N4728:22V	31a	-	-
1N4748A	Z-Di	22V,1W,Zzt=23Ω	-	Fch	-
1N4749	Z-Di	=1N4728:24V	31a	-	-
1N4749A	Z-Di	24V,1W,Zzt=25Ω	-	Fch	-
1N475	Z-Di	=1N471:7,1V	2c	-	-
1N4750	Z-Di	=1N4728:27V	31a	-	-
1N4750A	Z-Di	27V,1W,Zzt=35Ω	-	Fch	-
1N4751	Z-Di	=1N4728:30V	31a	-	-
1N4751A	Z-Di	30V,1W,Zzt=40Ω	-	Fch	-
1N4752	Z-Di	=1N4728:33V	31a	-	-
1N4752A	Z-Di	33V,1W,Zzt=45Ω	-	Fch	-
1N4753	Z-Di	=1N4728:36V	31a	-	-
1N4753A	Z-Di	36V,1W,Zzt=50Ω	-	Fch	-
1N4754	Z-Di	=1N4728:39V	31a	-	-
1N4754A	Z-Di	39V,1W,Zzt=60Ω	-	Fch	-
1N4755	Z-Di	=1N4728:43V	31a	-	-
1N4755A	Z-Di	43V,1W,Zzt=70Ω	-	Fch	-
1N4756	Z-Di	=1N4728:47V	31a	-	-
1N4756A	Z-Di	47V,1W,Zzt=80Ω	-	Fch	-
1N4757	Z-Di	=1N4728:51V	31a	-	-
1N4757A	Z-Di	51V,1W,Zzt=95Ω	-	Fch	-
1N4758	Z-Di	=1N4728:56V	31a	-	-
1N4758A	Z-Di	56V,1W,Zzt=110Ω	-	Fch	-
1N4759	Z-Di	=1N4728:62V	31a	-	-
1N4759A	Z-Di	62V,1W,Zzt=125Ω	-	Fch	-
1N476	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N4760	Z-Di	=1N4728:68V	31a	-	-
1N4760A	Z-Di	68V,1W,Zzt=150Ω	-	Fch	-
1N4761	Z-Di	=1N4728:75V	31a	-	-
1N4761A	Z-Di	75V,1W,Zzt=175Ω	-	Fch	-
1N4762	Z-Di	=1N4728:82V	31a	-	-
1N4762A	Z-Di	82V,1W,Zzt=200Ω	-	Fch	-
1N4763	Z-Di	=1N4728:91V	31a	-	-
1N4763A	Z-Di	91V,1W,Zzt=250Ω	-	Fch	-
1N4764	Z-Di	=1N4728:100V	31a	-	-
1N4764A	Z-Di	100V,1W,Zzt=350Ω	-	Fch	-
1N4765(A,B)	Ref-Di	9,1V,5%,0,25W	31a	USA,Sie,Tho	1N935
1N4766(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	1N936
1N4767(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	1N937
1N4768(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	1N938
1N4769(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	1N939
1N477	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N4770(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	-
1N4771(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	-
1N4772(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	-
1N4773(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	-
1N4774(A,B)	Ref-Di	9,1V,5%,0,25W	31a	-	-
1N4775(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3154
1N4776(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3155
1N4777(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3156
1N4778(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3157
1N4779(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	-
1N478	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N4780(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3154
1N4781(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3155
1N4782(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3156
1N4783(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	1N3157
1N4784(A,B)	Ref-Di	8,5V,5%,0,25W	31a	-	-
1N4785	Ge-Di	TV-Damper/Booster-Di,320V,7A	23	Rca	AY102
1N4786(A..D)	Si-Di	A=n10%,B=n5%,C=n2%,D=n1%	-		-
1N4786(A..D)	Si-Di	VHF-Tuning,25V,6,8pF(n20%)(4V)	31a	Tdy,Trw	-
1N4787(A..D)	Si-Di	=1N4786:8,2pF(4V)	31a	Tdy,Trw	-
1N4788(A..D)	Si-Di	=1N4786:10pF(4V)	31a	Tdy,Trw	-

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1N4789(A..D)	Si-Di	=1N4786:12pF(4V)	31a	Tdy,Trw	-
1N479	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N4790(A..D)	Si-Di	=1N4786:15pF(4V)	31a	Tdy,Trw	-
1N4791(A..D)	Si-Di	A=n10%,B=n5%,C=n2%,D=n1%	-		-
1N4791(A..D)	Si-Di	VHF-Tuning,20V,18pF(n20%)(4V)	31a	Tdy,Trw	-
1N4792(A..D)	Si-Di	=1N4791:22pF(4V)	31a	Tdy,Trw	-
1N4793(A..D)	Si-Di	=1N4791:27pF(4V)	31a	Tdy,Trw	-
1N4794(A..D)	Si-Di	=1N4791:33pF(4V)	31a	Tdy,Trw	-
1N4795(A..D)	Si-Di	=1N4791:39pF(4V)	31a	Tdy,Trw	-
1N4796(A..D)	Si-Di	=1N4791:47pF(4V)	31a	Tdy,Trw	-
1N4797(A..D)	Si-Di	=1N4791:56pF(4V)	31a	Tdy,Trw	-
1N4798(A..D)	Si-Di	=1N4791:68pF(4V)	31a	Tdy,Trw	-
1N4799(A..D)	Si-Di	=1N4791:82pF(4V)	31a	Tdy,Trw	-
1N48(N)	Ge-Di	Uni,80V,50mA,N:85V,40mA	31a	USA,Tho	AA117..118,AA132..133
1N480	Ge-Di	S,60V,35mA,<500ns	31a	USA	AAY28,AAZ15,AAZ17,1N276
1N4800(A..D)	Si-Di	=1N4791:100pF(4V)	31a	Tdy,Trw	-
1N4801(A..D)	Si-Di	=1N4786:100V	31a	Tdy,Trw	-
1N4802(A..D)	Si-Di	=1N4787:100V	31a	Tdy,Trw	-
1N4803(A..D)	Si-Di	=1N4788:100V	31a	Tdy,Trw	-
1N4804(A..D)	Si-Di	=1N4789:100V	31a	Tdy,Trw	-
1N4805(A..D)	Si-Di	=1N4790:100V	31a	Tdy,Trw	-
1N4806(A..D)	Si-Di	=1N4791:90V	31a	Tdy,Trw	-
1N4807(A..D)	Si-Di	=1N4792:90V	31a	Tdy,Trw	-
1N4808(A..D)	Si-Di	=1N4793:65V	31a	Tdy,Trw	-
1N4809(A..D)	Si-Di	=1N4794:60V	31a	Tdy,Trw	-
1N481	Ge-Di	Gl,200V,0,1A	-		-
1N4810(A..D)	Si-Di	=1N4795:55V	31a	Tdy,Trw	-
1N4811(A..D)	Si-Di	=1N4796:50V	31a	Tdy,Trw	-
1N4812(A..D)	Si-Di	=1N4797:40V	31a	Tdy,Trw	-
1N4813(A..D)	Si-Di	=1N4798:30V	31a	Tdy,Trw	-
1N4814(A..D)	Si-Di	=1N4799:20V	31a	Tdy,Trw	-
1N4815(A..D)	Si-Di	=1N4800:20V	31a	Tdy,Trw	-
1N4816(A)	Si-Di	Gl,50V,1,5A	31a	USA,Gie	BY226..227,BY251..255,1N5391..99,+
1N4817(A)	Si-Di	=1N4816:100V	31a	-	BY226..227,BY251..255,1N5392..99,+
1N4818(A)	Si-Di	=1N4816:200V	31a	-	BY226..227,BY251..255,1N5393..99,+
1N4819(A)	Si-Di	=1N4816:300V	31a	-	BY226..227,BY252..255,1N5394..99,+
1N482(A..C)	Si-Di	Uni,40V,0,1A,A..C:0,2A	31a	Fch,Tlx,++	BA127,BA187..190,BA215,BAY45,+
1N4820(A)	Si-Di	=1N4816:400V	31a	-	BY226..227,BY252..255,1N5395..99,+
1N4821(A)	Si-Di	=1N4816:500V	31a	-	BY226..227,BY253..255,1N5396..99,+
1N4822(A)	Si-Di	=1N4816:600V	31a	-	BY226..227,BY253..255,1N5397..99,+
1N4823	Si-Di	Gl,S,100V,1A,<100ns	34a	USA	BYV12..16,BYX92/100,EGP10B,+
1N4824	Si-Di	=1N4823:200V	34a	-	BYV13..16,BYX92/200,EGP10D,+
1N4825	Si-Di	=1N4823:400V	34a	-	BYT52G,BYV13..16,BYX92/400,+
1N4826	Si-Di	=1N4823:600V	34a	-	BYT52J,BYV14..16,BYV36C,+
1N4827	Ge-Di	S,30V,200ns	31a	USA	AAY28,1N631,1N633
1N4828	Si-St	1,1V(100mA),0,4W	31a	USA,Gen	-
1N4829	Si-St	=1N4828:1,87V(100mA)	31a	-	-
1N483(A..C)	Si-Di	=1N482(A..C):80V	31a	Fch,Tlx,++	BA188..190,BAW52,BAY19,BAY45,+
1N4830	Si-St	=1N4828:2,69V(100mA)	31a	-	-
1N4831	Z-Di	bidirektional,9,1V,20%,1,2W	31a	USA,Tlx	-
1N4831A...4860A	Z-Di	=1N4831..4860:10%	31a	-	-
1N4831A..4860A	Z-Di	=1N4831..4860:10%	31a	-	-
1N4831B...4860B	Z-Di	=1N4831..4860:5%	31a	-	-
1N4831B..4860B	Z-Di	=1N4831..4860:5%	31a	-	-
1N4832	Z-Di	=1N4831:10V	31a	-	-
1N4833	Z-Di	=1N4831:11V	31a	-	-
1N4834	Z-Di	=1N4831:12V	31a	-	-
1N4835	Z-Di	=1N4831:13V	31a	-	-
1N4836	Z-Di	=1N4831:15V	31a	-	-
1N4837	Z-Di	=1N4831:16V	31a	-	-
1N4838	Z-Di	=1N4831:18V	31a	-	-
1N4839	Z-Di	=1N4831:20V	31a	-	-
1N484(A..C)	Si-Di	=1N482(A..C):150V	31a	Fch,Tlx,++	BA189..190,BAW52,BAY20,BAY45,+
1N4840	Z-Di	=1N4831:22V	31a	-	-

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1N4841	Z-Di	=1N4831:24V	31a	-	-
1N4842	Z-Di	=1N4831:27V	31a	-	-
1N4843	Z-Di	=1N4831:30V	31a	-	-
1N4844	Z-Di	=1N4831:33V	31a	-	-
1N4845	Z-Di	=1N4831:36V	31a	-	-
1N4846	Z-Di	=1N4831:39V	31a	-	-
1N4847	Z-Di	=1N4831:43V	31a	-	-
1N4848	Z-Di	=1N4831:47V	31a	-	-
1N4849	Z-Di	=1N4831:51V	31a	-	-
1N485(A..C)	Si-Di	=1N482(A..C):200V	31a	Fch,Tlx,++	BA190,BAW52,BAY21,BAY46,+
1N4850	Z-Di	=1N4831:56V	31a	-	-
1N4851	Z-Di	=1N4831:62V	31a	-	-
1N4852	Z-Di	=1N4831:68V	31a	-	-
1N4853	Z-Di	=1N4831:75V	31a	-	-
1N4854	Z-Di	=1N4831:82V	31a	-	-
1N4855	Z-Di	=1N4831:91V	31a	-	-
1N4856	Z-Di	=1N4831:100V	31a	-	-
1N4857	Z-Di	=1N4831:110V	31a	-	-
1N4858	Z-Di	=1N4831:120V	31a	-	-
1N4859	Z-Di	=1N4831:130V	31a	-	-
1N486(A,B)	Si-Di	Uni,225V,0,1A,A,B:0,2A	31a	Gie,Tlx,++	BA157..159,BAY21,BAY46,BAY88..98
1N4860	Z-Di	=1N4831:150V	31a	-	-
1N4861	Si-Di	S,40V,3,5pF(0V),<1?s	31a	USA,Hit	BA127,BA147/50,BA187..190,+
1N4862	Si-Di	S,70V,<3,5pF(0V),<1?s	31a	USA,Hit	BA127,BA147/100,BA188..190,+
1N4863	Si-Di	SS,70V,0,2A,<2pF(0V),<7ns	31a	USA,Gen,Hit	BAW62,BAW76,BAX95,1N4148..49,+
1N4864	Si-Di	SS,125V,0,2A,<1,3pF(0V),<4ns	31a	USA,Gen,Hit	(BA203)
1N4865	Si-Di	kV-Gl,1,5kV,1,25A	-	USA	-
1N4866	Si-Di	=1N4865:2,5kV	-	-	-
1N4867	Si-Di	=1N4865:3kV	-	-	-
1N4868	Si-Di	=1N4865:5kV	-	-	-
1N4869	Si-Di	=1N4865:7,5kV	-	-	-
1N487(A,B)	Si-Di	=1N486(A,B):300V	31a	-	BA157..159,BAY21,BAY46,BAY88..90
1N4870	Si-Di	=1N4865:10kV	-	-	-
1N4871	Si-Di	=1N4865:12kV	-	-	-
1N4872	Si-Di	=1N4865:15kV	-	-	-
1N4873	Si-Di	=1N4865:20kV	-	-	-
1N4874	Si-Di	=1N4865:25kV	-	-	-
1N4875	Si-Di	=1N4865:30kV	-	-	-
1N4876	Si-Di	=1N4865:40kV	-	-	-
1N4877	Si-Di	=1N4865:50kV	-	-	-
1N4878	Si-Di	Gl-L,100V,100A(Tc=120o)	73a$	USA	1N3288..97
1N4879	Si-Di	Gl-L,100V,160A(Tc=120o)	73a$	USA	1N4587..96
1N488(A,B)	Si-Di	=1N486(A,B):380V	31a	-	BA158..159,BAY21,BAY88..90
1N4880	Si-Di	Gl-L,250V,160A(Tc=120o)	73a$	-	1N3735..44
1N4881	Z-Di	20V,10%,3W	31a	USA	BZT03/C,D20
1N4882	Z-Di	36V,10%,3W	31a	USA	BZT03/C,D,36
1N4883	Z-Di	12V,5%,3W	31a	USA	BZT03/C12
1N4884	Z-Di	=1N4881:5%	31a	-	BZT03/C20
1N4885	Si-Di	HF-Multiplier,150V,28..39pF(6V)	32	Phi	-
1N4886	Si-Di	HF-Multiplier,120V,28..39pF(6V)	32	Phi	-
1N4887	Si-Di	=1N4865:75kV	-	-	-
1N4888	Si-Di	SS,12V,<0,5ns	31a	Idc	BAY82,1N4244,1N4376
1N4889	Z-Di	62V,5%,5W	31a	Trw	BZV40/C62,BZV48/C62,1N5372
1N4890(A)	Ref-Di	6,35V,5%,0,4W	31a	USA,Sie	-
1N4891(A)	Ref-Di	6,35V,5%,0,4W	31a	-	-
1N4892(A)	Ref-Di	6,35V,5%,0,4W	31a	-	-
1N4893(A)	Ref-Di	6,35V,5%,0,4W	31a	-	-
1N4894(A)	Ref-Di	6,35V,5%,0,4W	31a	-	-
1N4895(A)	Ref-Di	6,35V,5%,0,4W	31a	-	-
1N4896(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	Mot,Sie,++	-
1N4897(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4898(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4899(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N49	Ge-Di	Uni,7SV	31a	USA,Tho	AA117..118,AA132..133,1N34,1N54

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1N490	Ge-Di	S,60V,35mA,<500ns	31a	USA	AAY28,AAZ15,AAZ17,1N276
1N4900(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4901(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4902(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4903(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4904(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4905(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4906(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4907(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4908(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4909(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4910(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4911(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4912(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4913(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4914(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4915(A)	Ref-Di	ra,12,8V,5%,0,4W	31a	-	-
1N4916(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4917(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4918(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4919(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4920(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4921(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4922(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4923(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4924(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4925(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4926(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4927(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4928(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4929(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4930(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4931(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4932(A)	Ref-Di	ra,19,2V,5%,0,4W	31a	-	-
1N4933(GP)	Si-Di	Gl,S,50V,1A,<200ns	31a	USA,EUR	BYT52A,BYX92/50,EGP10A,RGP10A,+
1N4934(GP)	Si-Di	=1N4933:100V	31a	-	BYT52B,BYX92/100,EGP10B,RGP10B,+
1N4935(GP)	Si-Di	=1N4933:200V	31a	-	BYT52D,BYX92/200,EGP10D,RGP10D,+
1N4936(GP)	Si-Di	=1N4933:400V	31a	-	BY201/4,BYT52G,BYX92/400,RGP10G+
1N4937(GP)	Si-Di	=1N4933:600V	31a	-	BY201/6,BYT52J,BYX92/600,RGP10J+
1N4938	Si-Di	=1N3070	31a	USA,Fch,Hit	→1N3070
1N4939	Ge-Di	UHF,Ka-Band-M,26..40GHz	Koax	Phi	-
1N4940	Ge-Di	UHF,X-Band-M,1..18GHz	Koax	Phi	-
1N4941	GaAs-Di	UHF-Tuning,6V,<0,4pF(6V)	Koax	Phi	-
1N4942(GP)	Si-Di	Gl,S,200V,1A,<150ns	31a	USA,Sie,Tho	BYT52D,BYX92/200,EGP10D,RGP10D,+
1N4943(GP)	Si-Di	=1N4942:300V	31a	-	BYT52G,BYX92/300,RGP10G,+
1N4944(GP)	Si-Di	=1N4942:400V	31a	-	BYT52G,BYX92/400,RGP10G,+
1N4945(GP)	Si-Di	=1N4942:500V	31a	-	BY201/6,BYT52J,RGP10J,+
1N4946(GP)	Si-Di	=1N4942:600V,<250ns	31a	-	BY201/6,BYT52J,RGP10J,+
1N4947(GP)	Si-Di	=1N4942:800V,<250ns	31a	-	BYV15..16,BYT52K,RGP10K,+
1N4948(GP)	Si-Di	=1N4942:1000V,<500ns	31a	-	BYV16,BYV38,BYT52M,RGP10M,+
1N4949	Si-Di	SS,35V,<3pF(0V),<0,3ns	31a	Idc,Inr	-
1N4950	Si-Di	SS,30V,<3,5pF(0V),<4ns	31a	USA	BA218,BAX13,BAX91,1N4148..49,+
1N4951	Si-Di	Dual,TV-HA-Synchr.20V,25mA,<2,3pF	7p	Gen	-
1N4952	Si-Di	=1N4951:50V	7p	Gen	-
1N4953	-Di	SS,30V,<1,5pF(0V)	Koax	Hew	-
1N4954	Z-Di	6,8V,5%,5W	31a	USA	BZV40/..,BZV48/..,1N5342..5388
1N4954A...4996A	Z-Di	=1N4954..4996:10%	31a	-	-
1N4954A..4996A..	Z-Di	=1N4954..4996:10%	31a	-	-
1N4954B...4996B	Z-Di	=1N4954..4996:20%	31a	-	-
1N4954B..4996B..	Z-Di	=1N4954..4996:20%	31a	-	-
1N4955	Z-Di	=1N4954:7,5V	31a	-	-
1N4956	Z-Di	=1N4954:8,2V	31a	-	-
1N4957	Z-Di	=1N4954:9,1V	31a	-	-
1N4958	Z-Di	=1N4954:10V	31a	-	-

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1N4959	Z-Di	=1N4954:11V	31a	-	-
1N4960	Z-Di	=1N4954:12V	31a	-	-
1N4961	Z-Di	=1N4954:13V	31a	-	-
1N4962	Z-Di	=1N4954:15V	31a	-	-
1N4963	Z-Di	=1N4954:16V	31a	-	-
1N4964	Z-Di	=1N4954:18V	31a	-	-
1N4965	Z-Di	=1N4954:20V	31a	-	-
1N4966	Z-Di	=1N4954:22V	31a	-	-
1N4967	Z-Di	=1N4954:24V	31a	-	-
1N4968	Z-Di	=1N4954:27V	31a	-	-
1N4969	Z-Di	=1N4954:30V	31a	-	-
1N497	Ge-Di	Uni,25V,80mA	31a	USA	AA135..136,1N270
1N4970	Z-Di	=1N4954:33V	31a	-	-
1N4971	Z-Di	=1N4954:36V	31a	-	-
1N4972	Z-Di	=1N4954:39V	31a	-	-
1N4973	Z-Di	=1N4954:43V	31a	-	-
1N4974	Z-Di	=1N4954:47V	31a	-	-
1N4975	Z-Di	=1N4954:51V	31a	-	-
1N4976	Z-Di	=1N4954:56V	31a	-	-
1N4977	Z-Di	=1N4954:62V	31a	-	-
1N4978	Z-Di	=1N4954:68V	31a	-	-
1N4979	Z-Di	=1N4954:75V	31a	-	-
1N498	Ge-Di	Uni,46V,70mA	31a	USA	AA136,1N270
1N4980	Z-Di	=1N4954:82V	31a	-	-
1N4981	Z-Di	=1N4954:91V	31a	-	-
1N4982	Z-Di	=1N4954:100V	31a	-	-
1N4983	Z-Di	=1N4954:110V	31a	-	-
1N4984	Z-Di	=1N4954:120V	31a	-	-
1N4985	Z-Di	=1N4954:130V	31a	-	-
1N4986	Z-Di	=1N4954:150V	31a	-	-
1N4987	Z-Di	=1N4954:160V	31a	-	-
1N4988	Z-Di	=1N4954:180V	31a	-	-
1N4989	Z-Di	=1N4954:200V	31a	-	-
1N499	Ge-Di	Uni,62V,80mA	31a	USA	AA136,1N270
1N4990	Z-Di	=1N4954:220V	31a	-	-
1N4991	Z-Di	=1N4954:240V	31a	-	-
1N4992	Z-Di	=1N4954:270V	31a	-	-
1N4993	Z-Di	=1N4954:300V	31a	-	-
1N4994	Z-Di	=1N4954:330V	31a	-	-
1N4995	Z-Di	=1N4954:360V	31a	-	-
1N4996	Z-Di	=1N4954:390V	31a	-	-
1N4997(R)	Si-Di	?1N4719	-	USA,Mot	→1N4719
1N4998(R)	Si-Di	?1N4720	-	USA,Mot	→1N4720
1N4999(R)	Si-Di	?1N4721	-	USA,Mot	→1N4721
1N5	Si-N	=ZXT11N15DF(Typ-Code/Stempel/marking)	35	Ztx	→ZXT11N15DF
1N50	Ge-Di	Uni,75V	31a	USA,Tho	AA117..118,AA132..133,1N34,1N54
1N500	Ge-Di	Uni,70V,80mA	31a	USA	1N270
1N5000(R)	Si-Di	?1N4722	-	USA,Mot	→1N4722
1N5001(R)	Si-Di	?1N4723	-	USA,Mot	→1N4723
1N5002(R)	Si-Di	?1N4724	-	USA,Mot	→1N4724
1N5003(R)	Si-Di	?1N4725	-	USA,Mot	→1N4725
1N5004	Si-Di	GI,100V,1A	34a	USA	BY126..127,BY133..134,1N4002..07,+
1N5005	Si-Di	=1N5004:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N5006	Si-Di	=1N5004:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N5007	Si-Di	=1N5004:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N5008	Z-Di	3,3V,10%,2,5W	31a	USA	BZD23/..,BZT03/..,BZX70/..
1N5008A..5051A	Z-Di	=1N5008..5051:5%	31a	-	-
1N5008A..5051A..	Z-Di	=1N5008..5051:5%	31a	-	-
1N5009	Z-Di	=1N5008:3,6V	31a	-	-
1N501	Ge-Di	Uni,92V,80mA	31a	USA	1N270
1N5010	Z-Di	=1N5008:3,9V	31a	-	-
1N5011	Z-Di	=1N5008:4,3V	31a	-	-
1N5012	Z-Di	=1N5008:4,7V	31a	-	-
1N5013	Z-Di	=1N5008:5,1V	31a	-	-

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1N5014	Z-Di	=1N5008:5,6V	31a	-	-
1N5015	Z-Di	=1N5008:6,2V	31a	-	-
1N5016	Z-Di	=1N5008:6,8V	31a	-	-
1N5017	Z-Di	=1N5008:7,5V	31a	-	-
1N5018	Z-Di	=1N5008:8,2V	31a	-	-
1N5019	Z-Di	=1N5008:9,1V	31a	-	-
1N502	Ge-Di	Uni,115V,70mA	31a	USA	1N270
1N5020	Z-Di	=1N5008:10V	31a	-	-
1N5021	Z-Di	=1N5008:11V	31a	-	-
1N5022	Z-Di	=1N5008:12V	31a	-	-
1N5023	Z-Di	=1N5008:13V	31a	-	-
1N5024	Z-Di	=1N5008:14V	31a	-	-
1N5025	Z-Di	=1N5008:15V	31a	-	-
1N5026	Z-Di	=1N5008:16V	31a	-	-
1N5027	Z-Di	=1N5008:17V	31a	-	-
1N5028	Z-Di	=1N5008:18V	31a	-	-
1N5029	Z-Di	=1N5008:19V	31a	-	-
1N503	Si-Di	Gl,50V,0,33A	-	old	BY126..127,BY133..135,1N4001..07,+
1N5030	Z-Di	=1N5008:20V	31a	-	-
1N5031	Z-Di	=1N5008:22V	31a	-	-
1N5032	Z-Di	=1N5008:24V	31a	-	-
1N5033	Z-Di	=1N5008:25V	31a	-	-
1N5034	Z-Di	=1N5008:27V	31a	-	-
1N5035	Z-Di	=1N5008:30V	31a	-	-
1N5036	Z-Di	=1N5008:33V	31a	-	-
1N5037	Z-Di	=1N5008:36V	31a	-	-
1N5038	Z-Di	=1N5008:39V	31a	-	-
1N5039	Z-Di	=1N5008:43V	31a	-	-
1N504	Si-Di	=1N503:100V	-		BY126..127,BY133..135,1N4002..07,+
1N5040	Z-Di	=1N5008:45V	31a	-	-
1N5041	Z-Di	=1N5008:47V	31a	-	-
1N5042	Z-Di	=1N5008:50V	31a	-	-
1N5043	Z-Di	=1N5008:51V	31a	-	-
1N5044	Z-Di	=1N5008:52V	31a	-	-
1N5045	Z-Di	=1N5008:56V	31a	-	-
1N5046	Z-Di	=1N5008:62V	31a	-	-
1N5047	Z-Di	=1N5008:68V	31a	-	-
1N5048	Z-Di	=1N5008:75V	31a	-	-
1N5049	Z-Di	=1N5008:82V	31a	-	-
1N505	Si-Di	=1N503:200V	-		BY126..127,BY133..134,1N4003..07,+
1N5050	Z-Di	=1N5008:91V	31a	-	-
1N5051	Z-Di	=1N5008:100V	31a	-	-
1N5052(A)	Si-Di	Gl,700V,1,5A	31a	USA	BY227,BYX85..86,GP15K,1N5398..99+
1N5053(A)	Si-Di	=1N5052:800V	31a	-	BY227,BYX85..86,GP15K,1N5398..99+
1N5054(A)	Si-Di	=1N5052:1000V	31a	-	BY227,BYX86,GP15M,1N5399,+
1N5055	Si-Di	Gl,100V,1A	31a	USA	BY126..127,BY133..135,1N4002..07,+
1N5056	Si-Di	=1N5055:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1N5057	Si-Di	=1N5055:300V,0,8A	31a	-	BY126..127,BY133..134,1N4004..07,+
1N5058	Si-Di	=1N5055:400V,0,8A	31a	-	BY126..127,BY133..134,1N4004..07,+
1N5059(GP)	Si-Di	Gl,contr.av.,200V,2A	31a	USA,EUR,Hit	BYD14D..M,BYW52..56
1N506	Si-Di	=1N503:300V	-		BY126..127,BY133..134,1N4004..07,+
1N5060(GP)	Si-Di	=1N5059:400V	31a	-	BYD14G..M,BYW53..56
1N5061(GP)	Si-Di	=1N5059:600V	31a	-	BYD14J..M,BYW54..56
1N5062(GP)	Si-Di	=1N5059:800V	31a	-	BYD14K..M,BYW55..56
1N5063	Z-Di	6,8V,5%,3W	31a	USA	BZT03/..
1N5064	Z-Di	=1N5063:7,5V	31a	-	-
1N5065	Z-Di	=1N5063:8,2V	31a	-	-
1N5066	Z-Di	=1N5063:9,1V	31a	-	-
1N5067	Z-Di	=1N5063:10V	31a	-	-
1N5068	Z-Di	=1N5063:11V	31a	-	-
1N5069	Z-Di	=1N5063:13V	31a	-	-
1N507	Si-Di	=1N503:400V	-		BY126..127,BY133..134,1N4004..07,+
1N5070	Z-Di	=1N5063:14V	31a	-	-
1N5071	Z-Di	=1N5063:15V	31a	-	-

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1N5072	Z-Di	=1N5063:16V	31a	-	-
1N5073	Z-Di	=1N5063:18V	31a	-	-
1N5074	Z-Di	=1N5063:22V	31a	-	-
1N5075	Z-Di	=1N5063:24V	31a	-	-
1N5076	Z-Di	=1N5063:27V	31a	-	-
1N5077	Z-Di	=1N5063:30V	31a	-	-
1N5078	Z-Di	=1N5063:33V	31a	-	-
1N5079	Z-Di	=1N5063:36V	31a	-	-
1N508	Si-Di	=1N503:600V	-		BY126..127,BY133..134,1N4005..07,+
1N5080	Z-Di	=1N5063:39V	31a	-	-
1N5081	Z-Di	=1N5063:40V	31a	-	-
1N5082	Z-Di	=1N5063:43V	31a	-	-
1N5083	Z-Di	=1N5063:45V	31a	-	-
1N5084	Z-Di	=1N5063:47V	31a	-	-
1N5085	Z-Di	=1N5063:50V	31a	-	-
1N5086	Z-Di	=1N5063:51V	31a	-	-
1N5087	Z-Di	=1N5063:56V	31a	-	-
1N5088	Z-Di	=1N5063:60V	31a	-	-
1N5089	Z-Di	=1N5063:62V	31a	-	-
1N509	Si-Di	=1N503:800V	-		BY127,BY133,BYW42,1N4006..07,+
1N5090	Z-Di	=1N5063:68V	31a	-	-
1N5091	Z-Di	=1N5063:70V	31a	-	-
1N5092	Z-Di	=1N5063:75V	31a	-	-
1N5093	Z-Di	=1N5063:80V	31a	-	-
1N5094	Z-Di	=1N5063:82V	31a	-	-
1N5095	Z-Di	=1N5063:91V	31a	-	-
1N5096	Z-Di	=1N5063:110V	31a	-	-
1N5097	Z-Di	=1N5063:120V	31a	-	-
1N5098	Z-Di	=1N5063:130V	31a	-	-
1N5099	Z-Di	=1N5063:140V	31a	-	-
1N51	Ge-Di	Dem,Uni,46V,30mA	31a	USA,Tho	AA113,1N34,1N54,1N60
1N510	Si-Di	=1N503:1000V	-		BY127,BY133,BYW43,1N4007,+
1N5100	Z-Di	=1N5063:160V	31a	-	-
1N5101	Z-Di	=1N5063:170V	31a	-	-
1N5102	Z-Di	=1N5063:180V	31a	-	-
1N5103	Z-Di	=1N5063:190V	31a	-	-
1N5104	Z-Di	=1N5063:200V	31a	-	-
1N5105	Z-Di	=1N5063:220V	31a	-	-
1N5106	Z-Di	=1N5063:240V	31a	-	-
1N5107	Z-Di	=1N5063:260V	31a	-	-
1N5108	Z-Di	=1N5063:270V	31a	-	-
1N5109	Z-Di	=1N5063:280V	31a	-	-
1N511	Si-Di	GI,50V,1A	-	old	BY126..127,BY133..135,1N4001..07,+
1N5110	Z-Di	=1N5063:300V	31a	-	-
1N5111	Z-Di	=1N5063:320V	31a	-	-
1N5112	Z-Di	=1N5063:330V	31a	-	-
1N5113	Z-Di	=1N5063:340V	31a	-	-
1N5114	Z-Di	=1N5063:360V	31a	-	-
1N5115	Z-Di	=1N5063:380V	31a	-	-
1N5116	Z-Di	=1N5063:390V	31a	-	-
1N5117	Z-Di	=1N5063:400V	31a	-	-
1N5118	Z-Di	14V,5%,5W	31a	USA	BZV40/..,BZV48/..,1N5351..5388
1N5119	Z-Di	=1N5118:40V	31a	-	-
1N512	Si-Di	=1N511:100V	-		BY126..127,BY133..135,1N4002..07,+
1N5120	Z-Di	=1N5118:45V	31a	-	-
1N5121	Z-Di	=1N5118:50V	31a	-	-
1N5122	Z-Di	=1N5118:60V	31a	-	-
1N5123	Z-Di	=1N5118:70V	31a	-	-
1N5124	Z-Di	=1N5118:80V	31a	-	-
1N5125	Z-Di	=1N5118:90V	31a	-	-
1N5126	Z-Di	=1N5118:140V	31a	-	-
1N5127	Z-Di	=1N5118:170V	31a	-	-
1N5128	Z-Di	=1N5118:190V	31a	-	-
1N5129	Z-Di	=1N5118:260V	31a	-	-

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1N513	Si-Di	=1N511:200V	-		BY126..127,BY133..134,1N4003..07,+
1N5130	Z-Di	=1N5118:280V	31a	-	-
1N5131	Z-Di	=1N5118:320V	31a	-	-
1N5132	Z-Di	=1N5118:340V	31a	-	-
1N5133	Z-Di	=1N5118:380V	31a	-	-
1N5134	Z-Di	=1N5118:400V	31a	-	-
1N5136(A)	Si-Di	A:n10%	-		-
1N5136(A)	Si-Di	VHF-Tuning,60V,1pF(n20%)(4V)	31a	Cod	-
1N5137(A)	Si-Di	=1N5136:2,2pF(4V)	31a	Cod	-
1N5138(A)	Si-Di	=1N5136:3,3pF(4V)	31a	Cod	-
1N5139(A)	Si-Di	A:n5%	-		-
1N5139(A)	Si-Di	VHF-Tuning,60V,6,8pF(4V)	31a	USA,Mot,Tho	-
1N514	Si-Di	=1N511:300V	-		BY126..127,BY133..134,1N4004..07,+
1N5140(A)	Si-Di	=1N5139:10pF(4V)	31a	USA,Mot,Tho	-
1N5141(A)	Si-Di	=1N5139:12pF(4V)	31a	USA,Mot,Tho	-
1N5142(A)	Si-Di	=1N5139:15pF(4V)	31a	USA,Mot,Tho	-
1N5143(A)	Si-Di	=1N5139:18pF(4V)	31a	USA,Mot,Tho	-
1N5144(A)	Si-Di	=1N5139:22pF(4V)	31a	USA,Mot,Tho	-
1N5145(A)	Si-Di	=1N5139:27pF(4V)	31a	USA,Mot,Tho	-
1N5146(A)	Si-Di	=1N5139:33pF(4V)	31a	USA,Mot,Tho	-
1N5147(A)	Si-Di	=1N5139:39pF(4V)	31a	USA,Mot,Tho	-
1N5148(A)	Si-Di	=1N5139:47pF(4V)	31a	USA,Mot,Tho	-
1N5149(A)	Si-Di	80V,11,5pF(6V),PQ>11W(0,5→1GHz)	-		-
1N5149(A)	Si-Di	Step-recovery,UHF-Multiplier(=MV1806C)	Koax	Fer,Mot,Pal	-
1N515	Si-Di	=1N511:400V	-		BY126..127,BY133..134,1N4004..07,+
1N5150(A)	Si-Di	80V,11,5pF(6V),PQ>24W(0,5→1GHz)	-		-
1N5150(A)	Si-Di	Step-recovery,UHF-Multiplier(=MV1807C)	Koax	Fer,Mot,Pal	-
1N5151	Si-Di	75V,5,8pF(6V),PQ>6W(1→2GHz)	-		-
1N5151	Si-Di	Step-recovery,UHF-Multiplier(=MV1808A)	Koax	Mot,Phi,++	-
1N5152(A)	Si-Di	75V,5,4..6,6pF(6V),PQ>7,2W(1→2GHz)	-		-
1N5152(A)	Si-Di	Step-recovery,UHF-Multiplier(=MV1808B)	Koax	Mot,Phi,++	-
1N5153(A)	Si-Di	75V,5,8..7pF(6V),PQ>7,2W(1→2GHz)	-		-
1N5153(A)	Si-Di	Step-recovery,UHF-Multiplier(=MV1808C)	Koax	Mot,Phi,++	-
1N5154	Si-Di	35V,2,1pF(6V),PQ>2W(2→6GHz)	-		-
1N5154	Si-Di	Step-recovery,UHF-Multiplier(=MV1810A)	Koax	Mot,Phi,++	-
1N5155(A)	Si-Di	35V,1,9pF(6V),PQ>2W(2→6GHz)	-		-
1N5155(A)	Si-Di	Step-recovery,UHF-Multiplier(=MV1810B)	Koax	Mot,Phi,++	-
1N5156	Si-Di	20V,0,6..1pF(6V),PQ>1W(5→10GHz)	-		-
1N5156	Si-Di	Step-recovery,UHF-Multiplier(=MV1812A)	Koax	Mot,Phi,++	-
1N5157	Si-Di	20V,0,6..1pF(6V),PQ>1W(5→10GHz)	-		-
1N5157	Si-Di	Step-recovery,UHF-Multiplier(=MV1812B)	Koax	Mot,Phi,++	-
1N5158	Trigger-Di	Ub=8..10V,Ib<0,05mA,Itsm=10A	31a	Mot	-
1N5159	Trigger-Di	=1N5158:Ub=9..11V	31a	-	-
1N516	Si-Di	=1N511:600V	-		BY126..127,BY133..134,1N4005..07,+
1N5160	Trigger-Di	=1N5158:Ub=10..12V	31a	-	-
1N5161	Si-Di	Rauschdiode/noise diode,260V,0,6W	31a	Sol	-
1N5162	Si-Di	Gl-L,1200V,150A(Tc=150o)	73a$	USA	1N4595..96
1N5163	Si-Di	Snap-off-Diode,SS,35V,<10pF,<0,5ns	31a	Hew	-
1N5164	Si-Di	Snap-off-Diode,SS,35V,<10pF,<0,4ns	31a	Hew	-
1N5165(A)	Si-Di	Schottky-Di,HF/S,30V,<1pF(0V)	31a	Hew	-
1N5166(A)	Si-Di	Schottky-Di,HF/S,30V,<1pF(0V)	31a	Hew	-
1N5167(A)	Si-Di	Schottky-Di,HF/S,20V,<1pF(0V)	31a	Hew	-
1N5168	Si-Di	Schottky-Di,HF	31a	Hew	-
1N5169	Si-Di	Schottky-Di,HF	31a	Hew	-
1N517	Si-Di	=1N511:800V	-		BY127,BY133,BYW42,1N4006..07,+
1N5170	Si-Di	Gl,15V,2A	31a	USA	BY251..255,BYW52..56,1N5400..08,+
1N5171	Si-Di	=1N5170:50V	31a	-	BY251..255,BYW52..56,1N5400..08,+
1N5172	Si-Di	=1N5170:100V	31a	-	BY251..255,BYW52..56,1N5401..08,+
1N5173	Si-Di	=1N5170:300V	31a	-	BY252..255,BYW53..56,1N5404..08,+
1N5174	Si-Di	=1N5170:400V	31a	-	BY252..255,BYW53..56,1N5404..08,+
1N5175	Si-Di	=1N5170:500V	31a	-	BY253..255,BYW54..56,1N5406..08,+
1N5176	Si-Di	=1N5170:600V	31a	-	BY253..255,BYW54..56,1N5406..08,+
1N5177	Si-Di	=1N5170:800V	31a	-	BY254..255,BYW55..56,1N5407..08,+
1N5178	Si-Di	=1N5170:1000V	31a	-	BY255,BYW56,GP20M,1N5408,+

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1N5179	Si-St	2,8V(1mA),0,4W	31a	Gen,Idc	BZ102/2V8,BZV86/2V6,BZX75/C2V8
1N518	Si-Di	=1N511:1000V	-		BY127,BY133,BYW43,1N4007,+
1N5180	Si-Di	Gl,120V,4A	31a	Sem,Trw	BY500-200,MR752..760,MR822..826,+
1N5181	Si-Di	kV-Gl,4kV,0,1A	31a	USA,Tho	HVG4,1N1734
1N5182	Si-Di	=1N5181:5kV	31a	-	HVG5,1N1734
1N5183	Si-Di	=1N5181:7,5kV	31a	-	BYX90
1N5184	Si-Di	=1N5181:10kV	31a	-	1N3052
1N5185(A)	Si-Di	Gl,S,50V,3(A:4)A,<250ns	31a	USA,Gie	BY500-100,BYV61..63,MR820..826,+
1N5186(A)	Si-Di	=1N5185:100V	31a	-	BY500-100,BYV62..63,MR821..826,+
1N5187(A)	Si-Di	=1N5185:200V	31a	-	BY500-200,EGP500,FES0,MR822..826
1N5188(A)	Si-Di	=1N5185:400V,<300ns	31a	-	BY500-400,MR824..826
1N5189(A)	Si-Di	=1N5185:500V,<350ns	31a	-	BY500-600,MR826
1N519	Si-Di	Gl,50V,1,25A	-	old	BY126..127,BY133..135,1N4001..07,+
1N5190(A)	Si-Di	=1N5185:600V,<400ns	31a	-	BY500-600,MR826
1N5194	Si-Di	Gl,Uni,80V,0,2A	31a	USA,Tix	BA157..159,BA188..190,BAY19..20,+
1N5195	Si-Di	=1N5194:200V	31a	-	BA157..159,BA190,BAY21,+
1N5196	Si-Di	=1N5194:250V	31a	-	BA157..159,BAY46,BAY88..90,+
1N5197	Si-Di	Gl,50V,3A	31a	USA	BY251..255,BYW17/100,1N5400..08,+
1N5198	Si-Di	=1N5197:100V	31a	-	BY251..255,BYW17/100,1N5401..08,+
1N5199	Si-Di	=1N5197:200V	31a	-	BY251..255,BYW17/200,1N5402..08,+
1N52(A)	Ge-Di	Uni,80V,50mA,A:50V	31a	USA,Tho	AA117..118,AA132..133
1N520	Si-Di	=1N519:100V	-		BY126..127,BY133..135,1N4002..07,+
1N5200	Si-Di	=1N5197:400V	31a	-	BY252..255,BYW17/400,1N5404..08,+
1N5201	Si-Di	=1N5197:600V	31a	-	BY253..255,BYW17/600,1N5406..08,+
1N5206	Si-Di	Gl,Uni,440V,2A	31a	Sem,Trw	BY253..255,BYW54..56,1N5061..62,+
1N5207	Si-Di	Gl,Uni,440V,4A	31a	Sem,Trw	BY500-600,MR756..760,MR826
1N5208	Si-Di	Uni,70V,0,075A	31a	Sem,Tix	BA147/100,BA188..190,1N5606..09,+
1N5209	Si-Di	Uni,150V,0,055A	31a	Sem,Tix	BA147/150,BA189..190,1N5606..07,+
1N521	Si-Di	=1N519:200V	-		BY126..127,BY133..134,1N4003..07,+
1N5210	Si-Di	Uni,200V,0,04A	31a	-	BA147/230,BAY21,BAY88..90,+
1N5211	Si-Di	Gl,200V,1A	34a	Rca,Sem,Ssi	BY126..127,BY133..134,1N4003..07,+
1N5212	Si-Di	=1N5211:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N5213	Si-Di	=1N5211:600V	34a	-	BY126..127,BY133..134,1N4005..07,+
1N5214	Si-Di	=1N5211:800V	34a	-	BY127,BY133,BY227,1N4006..07,+
1N5215	Si-Di	=1N5211:	34a(Iso)	-	→1N5211
1N5216	Si-Di	=1N5212:	34a(Iso)	-	→1N5212
1N5217	Si-Di	=1N5213:	34a(Iso)	-	→1N5213
1N5218	Si-Di	=1N5214:	34a(Iso)	-	→1N5214
1N5219	Si-Di	SS,30V,<1,5pF(0V),<2ns	31a	Msc,Sem	BA218,BAX13,BAX91,1N4148..49,+
1N522	Si-Di	=1N519:300V	-		BY126..127,BY133..134,1N4004..07,+
1N5220	Si-Di	SS,30V,<0,75pF(0V),<0,7ns	31a	Msc,Sem	-
1N5221	Z-Di	2,4V,20%,0,5W	31a	USA,EUR,JAP	BZX55/..,BZX83/..,ZPD..,1N5985..6031+
1N5221A...5281A	Z-Di	=1N5221..5281:10%	31a	-	-
1N5221A..5281A	Z-Di	=1N5221..5281:2,4..200V,0,5W,10%	31a	-	-
1N5221B...5281B	Z-Di	=1N5221..5281:5%	31a	-	-
1N5221B..5281B	Z-Di	=1N5221..5281:2,4..200V,0,5W,5%	31a	Fch	-
1N5222	Z-Di	=1N5221:2,5V	31a	-	-
1N5222B	Z-Di	2.5V,0.5W,5%,Zzt=30Ω	31a	Fairchild	-
1N5223	Z-Di	=1N5221:2,7V	31a	-	-
1N5223B	Z-Di	2.7V,0.5W,5%,Zzt=30Ω	31a	Fairchild	-
1N5224	Z-Di	=1N5221:2,8V	31a	-	-
1N5224B	Z-Di	2.8V,0.5W,5%,Zzt=30Ω	31a	Fairchild	-
1N5225	Z-Di	=1N5221:3,0V	31a	-	-
1N5225B	Z-Di	3V,0.5W,Zzt=29Ω	-	Fairchild	-
1N5226	Z-Di	=1N5221:3,3V	31a	-	-
1N5226B	Z-Di	3.3V,0.5W,Zzt=28Ω	-	Fairchild	-
1N5227	Z-Di	=1N5221:3,6V	31a	-	-
1N5227B	Z-Di	3.6V,0.5W,Zzt=24Ω	-	Fairchild	-
1N5228	Z-Di	=1N5221:3,9V	31a	-	-
1N5228B	Z-Di	Vreg,3.9V,0.5W,Zzt=23Ω	-	Fairchild	-
1N5229	Z-Di	=1N5221:4,3V	31a	-	-
1N5229B	Z-Di	Vreg,4.3V,0.5W,Zzt=22Ω	-	Fairchild	-
1N523	Si-Di	=1N519:400V	-		BY126..127,BY133..134,1N4004..07,+
1N5230	Z-Di	=1N5221:4,7V	31a	-	-

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1N5230B	Z-Di	Vreg,4.7V,0.5W,Zzt=19Ω	-	Fairchild	-
1N5231	Z-Di	=1N5221:5,1V	31a	-	-
1N5231B	Z-Di	Vreg,5.1V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5231C	Z-Di	Vreg,5.2V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5232	Z-Di	=1N5221:5,6V	31a	-	-
1N5232B	Z-Di	5.6V,0.5W,Zzt=11Ω	-	Fairchild	-
1N5233	Z-Di	=1N5221:6,0V	31a	-	-
1N5233B	Z-Di	6V,0.5W,Zzt=7Ω	-	Fairchild	-
1N5234	Z-Di	=1N5221:6,2V	31a	-	-
1N5234B	Z-Di	6.2V,0.5W,Zzt=7Ω	-	Fairchild	-
1N5235	Z-Di	=1N5221:6,8V	31a	-	-
1N5235B	Z-Di	6.8V,0.5W,Zzt=5Ω	-	Fairchild	-
1N5235BT	Z-Di	6.8V,0.5W,Zzt=5Ω	-	Fairchild	-
1N5236	Z-Di	=1N5221:7,5V	31a	-	-
1N5236B	Z-Di	7.5V,0.5W,Zzt=6Ω	-	Fairchild	-
1N5236BT	Z-Di	7.5V,0.5W,Zzt=6Ω	-	Fairchild	-
1N5237	Z-Di	=1N5221:8,2V	31a	-	-
1N5237B	Z-Di	8.2V,0.5W,Zzt=8Ω	-	Fairchild	-
1N5237BT	Z-Di	8.2V,0.5W,Zzt=8Ω	-	Fairchild	-
1N5238	Z-Di	=1N5221:8,7V	31a	-	-
1N5238B	Z-Di	8.7V,0.5W,Zzt=8Ω	-	Fairchild	-
1N5238BT	Z-Di	8.7V,0.5W,Zzt=8Ω	-	Fairchild	-
1N5239	Z-Di	=1N5221:9,1V	31a	-	-
1N5239B	Z-Di	9.1V,0.5W,Zzt=10Ω	-	Fairchild	-
1N5239BT	Z-Di	9.1V,0.5W,Zzt=10Ω	-	Fairchild	-
1N524	Si-Di	=1N519:600V	-		BY126..127,BY133..134,1N4005..07,+
1N5240	Z-Di	=1N5221:10V	31a	-	-
1N5240B	Z-Di	10V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5240BT	Z-Di	10V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5241	Z-Di	=1N5221:11V	31a	-	-
1N5241B	Z-Di	11V,0.5W,Zzt=22Ω	-	Fairchild	-
1N5241BT	Z-Di	11V,0.5W,Zzt=22Ω	-	Fairchild	-
1N5242	Z-Di	=1N5221:12V	31a	-	-
1N5242B	Z-Di	12V,0.5W,Zzt=30Ω	-	Fairchild	-
1N5242BT	Z-Di	12V,0.5W,Zzt=30Ω	-	Fairchild	-
1N5243	Z-Di	=1N5221:13V	31a	-	-
1N5243B	Z-Di	13V,0.5W,Zzt=13Ω	-	Fairchild	-
1N5243BT	Z-Di	13V,0.5W,Zzt=13Ω	-	Fairchild	-
1N5244	Z-Di	=1N5221:14V	31a	-	-
1N5244B	Z-Di	14V,0.5W,Zzt=15Ω	-	Fairchild	-
1N5244BT	Z-Di	14V,0.5W,Zzt=15Ω	-	Fairchild	-
1N5245	Z-Di	=1N5221:15V	31a	-	-
1N5245B	Z-Di	15V,0.5W,Zzt=16Ω	-	Fairchild	-
1N5245BT	Z-Di	15V,0.5W,Zzt=16Ω	-	Fairchild	-
1N5246	Z-Di	=1N5221:16V	31a	-	-
1N5246B	Z-Di	16V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5246BT	Z-Di	16V,0.5W,Zzt=17Ω	-	Fairchild	-
1N5247	Z-Di	=1N5221:17V	31a	-	-
1N5247B	Z-Di	17V,0.5W,Zzt=19Ω	-	Fairchild	-
1N5247BT	Z-Di	17V,0.5W,Zzt=19Ω	-	Fairchild	-
1N5248	Z-Di	=1N5221:18V	31a	-	-
1N5248B	Z-Di	18V,0.5W,Zzt=21Ω	-	Fairchild	-
1N5248BT	Z-Di	18V,0.5W,Zzt=21Ω	-	Fairchild	-
1N5249	Z-Di	=1N5221:19V	31a	-	-
1N5249B	Z-Di	19V,0.5W,Zzt=23Ω	-	Fairchild	-
1N5249BT	Z-Di	19V,0.5W,Zzt=23Ω	-	Fairchild	-
1N525	Si-Di	=1N519:800V	-		BY127,BY133,BYW42,1N4006..07,+
1N5250	Z-Di	=1N5221:20V	31a	-	-
1N5250B	Z-Di	20V,0.5W,Zzt=25Ω	-	Fairchild	-
1N5250BT	Z-Di	20V,0.5W,Zzt=25Ω	-	Fairchild	-
1N5251	Z-Di	=1N5221:22V	31a	-	-
1N5251B	Z-Di	22V,0.5W,Zzt=29Ω	-	Fairchild	-
1N5252	Z-Di	=1N5221:24V	31a	-	-
1N5252B	Z-Di	24V,0.5W,Zzt=33Ω	-	Fairchild	-

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1N5253	Z-Di	=1N5221:25V	31a	-	-
1N5253B	Z-Di	25V,0.5W,Zzt=35Ω	-	Fairchild	-
1N5254	Z-Di	=1N5221:27V	31a	-	-
1N5254B	Z-Di	27V,0.5W,Zzt=41Ω	-	Fairchild	-
1N5255	Z-Di	=1N5221:28V	31a	-	-
1N5255B	Z-Di	28V,0.5W,Zzt=44Ω	-	Fairchild	-
1N5256	Z-Di	=1N5221:30V	31a	-	-
1N5256B	Z-Di	30V,0.5W,Zzt=49Ω	-	Fairchild	-
1N5257	Z-Di	=1N5221:33V	31a	-	-
1N5257B	Z-Di	33V,0.5W,Zzt=58Ω	-	Fairchild	-
1N5258	Z-Di	=1N5221:36V	31a	-	-
1N5258B	Z-Di	36V,0.5W,Zzt=70Ω	-	Fairchild	-
1N5259	Z-Di	=1N5221:39V	31a	-	-
1N5259B	Z-Di	39V,0.5W,Zzt=80Ω	-	Fairchild	-
1N526	Si-Di	=1N519:1000V	-		BY127,BY133,BYW43,1N4007,+
1N5260	Z-Di	=1N5221:43V	31a	-	-
1N5260B	Z-Di	43V,0.5W,Zzt=93Ω	-	Fairchild	-
1N5261	Z-Di	=1N5221:47V	31a	-	-
1N5261B	Z-Di	47V,0.5W,Zzt=105Ω	-	Fairchild	-
1N5262	Z-Di	=1N5221:51V	31a	-	-
1N5262B	Z-Di	51V,0.5W,Zzt=125Ω	-	Fairchild	-
1N5263	Z-Di	=1N5221:56V	31a	-	-
1N5263B	Z-Di	56V,0.5W,Zzt=150Ω	-	Fairchild	-
1N5264	Z-Di	=1N5221:60V	31a	-	-
1N5264B	Z-Di	60V,0.5W,Zzt=170Ω	-	Fairchild	-
1N5265	Z-Di	=1N5221:62V	31a	-	-
1N5265B	Z-Di	62V,0.5W,Zzt=230Ω	-	Fairchild	-
1N5266	Z-Di	=1N5221:68V	31a	-	-
1N5266B	Z-Di	68V,0.5W,Zzt=230Ω	-	Fairchild	-
1N5267	Z-Di	=1N5221:75V	31a	-	-
1N5267B	Z-Di	75V,0.5W,Zzt=270Ω	-	Fairchild	-
1N5268	Z-Di	=1N5221:82V	31a	-	-
1N5268B	Z-Di	85V,0.5W,Zzt=330Ω	-	Fairchild	-
1N5269	Z-Di	=1N5221:87V	31a	-	-
1N5269B	Z-Di	87V,0.5W,Zzt=370Ω	-	Fairchild	-
1N527	Ge-Di	Uni,10V,Ifsm=0,1A	31a	USA	AA112..114,AA116,AA119,1N60,+
1N5270	Z-Di	=1N5221:91V	31a	-	-
1N5270B	Z-Di	91V,0.5W,Zzt=400Ω	-	Fairchild	-
1N5271	Z-Di	=1N5221:100V	31a	-	-
1N5271B	Z-Di	100V,0.5W,Zzt=500Ω	-	Fairchild	-
1N5272	Z-Di	=1N5221:110V	31a	-	-
1N5272B	Z-Di	110V,0.5W,Zzt=750Ω	-	Fairchild	-
1N5273	Z-Di	=1N5221:120V	31a	-	-
1N5274	Z-Di	=1N5221:130V	31a	-	-
1N5275	Z-Di	=1N5221:140V	31a	-	-
1N5276	Z-Di	=1N5221:150V	31a	-	-
1N5277	Z-Di	=1N5221:160V	31a	-	-
1N5278	Z-Di	=1N5221:170V	31a	-	-
1N5279	Z-Di	=1N5221:180V	31a	-	-
1N5279B	Z-Di	180V,0.5W	-	Fairchild	-
1N5280	Z-Di	=1N5221:190V	31a	-	-
1N5281	Z-Di	=1N5221:200V	31a	-	-
1N5282(A)	Si-Di	SS,80V,0,2A,<2,5pF(0V),<4ns	31a	USA	BAW62,BAW76,BAX95,1N4148..49,+
1N5283	Si-Di	FED,Strom-Stabi/current reg.0,6W	31a	USA,Mot	-
1N5283	Si-Di	Uf=25V(0,22mA),>25Me,Ulim<1V(80% If)	-		-
1N5284	Si-Di	=1N5283:Uf=25V(240?A),>19Me,Ulim<1V	31a	-	-
1N5285	Si-Di	=1N5283:Uf=25V(270?A),>14Me,Ulim<1V	31a	-	-
1N5286	Si-Di	=1N5283:Uf=25V(300?A),>9Me,Ulim<1V	31a	-	-
1N5287	Si-Di	=1N5283:Uf=25V(330?A),>6,6Me,Ulim<1V	31a	-	-
1N5288	Si-Di	=1N5283:Uf=25V(390?A),>4,1Me,<1,05V	31a	-	-
1N5289	Si-Di	=1N5283:Uf=25V(430?A),>3,3Me,<1,05V	31a	-	-
1N5290	Si-Di	=1N5283:Uf=25V(470?A),>2,7Me,<1,05V	31a	-	-
1N5291	Si-Di	=1N5283:Uf=25V(560?A),>1,9Me,<1,1V	31a	-	-
1N5292	Si-Di	=1N5283:Uf=25V(620?A),>1,55Me,<1,13	31a	-	-

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1N5293	Si-Di	=1N5283: Uf=25V(680?A), >1,35Me, <1,15	31a	-	-
1N5294	Si-Di	=1N5283: Uf=25V(750?A), >1,15Me, <1,2V	31a	-	-
1N5295	Si-Di	=1N5283: Uf=25V(820?A), >1Me, <1,25V	31a	-	-
1N5296	Si-Di	=1N5283: Uf=25V(910?A), >880ke, <1,29V	31a	-	-
1N5297	Si-Di	=1N5283: Uf=25V(1mA), >800ke, <1,35V	31a	-	-
1N5298	Si-Di	=1N5283: Uf=25V(1,1mA), >700ke, <1,4V	31a	-	-
1N5299	Si-Di	=1N5283: Uf=25V(1,2mA), >640ke, <1,45V	31a	-	-
1N52A1	Si-Di	=1N44A1: 15kV	-	Tos	-
1N53	Si-Di	UHF, Ka-Band-M, 34,860GHz	Koax	USA	-
1N530	Si-Di	Gl, 100V, 0,3A	34a	Sem, Sld, Tlx	BA157..159, BY402..405, 1N4002..07, +
1N5300	Si-Di	=1N5283: Uf=25V(1,3mA), >580ke, <1,5V	31a	-	-
1N5301	Si-Di	=1N5283: Uf=25V(1,4mA), >540ke, <1,55V	31a	-	-
1N5302	Si-Di	=1N5283: Uf=25V(1,5mA), >510ke, <1,6V	31a	-	-
1N5303	Si-Di	=1N5283: Uf=25V(1,6mA), >475ke, <1,65V	31a	-	-
1N5304	Si-Di	=1N5283: Uf=25V(1,8mA), >420ke, <1,75V	31a	-	-
1N5305	Si-Di	=1N5283: Uf=25V(2mA), >395ke, <1,8SV	31a	-	-
1N5306	Si-Di	=1N5283: Uf=25V(2,2mA), >370ke, <1,95V	31a	-	-
1N5307	Si-Di	=1N5283: Uf=25V(2,4mA), >345ke, <2V	31a	-	-
1N5308	Si-Di	=1N5283: Uf=25V(2,7mA), >320ke, <2,15V	31a	-	-
1N5309	Si-Di	=1N5283: Uf=25V(3mA), >300ke, <2,25V	31a	-	-
1N531	Si-Di	=1N530: 200V	34a	-	BA157..159, BY403..405, 1N4003..07, +
1N5310	Si-Di	=1N5283: Uf=25V(3,3mA), >280ke, <2,35V	31a	-	-
1N5311	Si-Di	=1N5283: Uf=25V(3,6mA), >265ke, <2,5V	31a	-	-
1N5312	Si-Di	=1N5283: Uf=25V(3,9mA), >255ke, <2,6V	31a	-	-
1N5313	Si-Di	=1N5283: Uf=25V(4,3mA), >245ke, <2,75V	31a	-	-
1N5314	Si-Di	=1N5283: Uf=25V(4,7mA), >235ke, <2,9V	31a	-	-
1N5315	Si-Di	SS, 100V, 0,2A, <2,5pF(0V), <4ns	31a	Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5316	Si-Di	SS, 100V, 0,135A, <2pF(0V), <4ns	31a	Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5317	Si-Di	SS, 80V, 0,125A, <2,5pF(0V), <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5318	Si-Di	SS, 75V, 0,125A, <2,5pF(0V), <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5319	Si-Di	SS, 40V, 0,1A, <3,5pF(0V), <4ns	31a	Fch, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N532	Si-Di	=1N530: 300V	34a	-	BA157..159, BY404..405, 1N4004..07, +
1N5320	Si-Di	S, 120V, 1A, <250ns	31a	USA	BY201/2, BY296..299, BYX58/200, +
1N5321	Si-Di	Schottky-Di, 30V, Uf<1V(50mA), <1pF	31a	Sol	-
1N5322	Si-Di	Schottky-Di, 30V, Uf<1V(35mA), <1pF	31a	Sol	-
1N5323	Si-Di	Schottky-Di, 20V, Uf<1V(35mA), <1pF	31a	Sol	-
1N5324	Si-Di	kV-Gl, 15k, 0,01A	31a	USA	HS10
1N5326	Si-Di	Gl, 200V, 12A(Tc=100o)	31a	Trw	-
1N5329	Si-Di	kV-Gl, 6kV, 0,135A	31a	Sem	BYX90, 1N5183
1N533	Si-Di	=1N530: 400V	34a	-	BA157..159, BY404..405, 1N4004..07, +
1N5330	Si-Di	Gl, 1500V, 0,54A	31a	Sem	BY269, DM513, EM516, GP10W, +
1N5331	Si-Di	Gl-L, 1200V, 12A(Tc=150o)	32a$	USA, Gen	BYW88/1200, TN4511
1N5332	Si-Di	Gl-L, 1200V, 35A(Tc=140o)	32a$	USA, Gen	1N4530
1N5333	Z-Di	3,3V, 20%, 5W	31a	USA, Mot, Sie	BZV40/.., BZV48/..
1N5333A..5388A	Z-Di	=1N5333..5388: 10%	31a	-	-
1N5333B..5388B	Z-Di	=1N5333..5388: 5%	31a	-	-
1N5334	Z-Di	=1N5333: 3,6V	31a	-	-
1N5335	Z-Di	=1N5333: 3,9V	31a	-	-
1N5336	Z-Di	=1N5333: 4,3V	31a	-	-
1N5337	Z-Di	=1N5333: 4,7V	31a	-	-
1N5338	Z-Di	=1N5333: 5,1V	31a	-	-
1N5339	Z-Di	=1N5333: 5,6V	31a	-	-
1N534	Si-Di	=1N530: 500V	34a	-	BA158..159, BY405, 1N4005..07, +
1N5340	Z-Di	=1N5333: 6V	31a	-	-
1N5341	Z-Di	=1N5333: 6,2V	31a	-	-
1N5342	Z-Di	=1N5333: 6,8V	31a	-	-
1N5343	Z-Di	=1N5333: 7,5V	31a	-	-
1N5344	Z-Di	=1N5333: 8,2V	31a	-	-
1N5345	Z-Di	=1N5333: 8,7V	31a	-	-
1N5346	Z-Di	=1N5333: 9,1V	31a	-	-
1N5347	Z-Di	=1N5333: 10V	31a	-	-
1N5348	Z-Di	=1N5333: 11V	31a	-	-
1N5349	Z-Di	=1N5333: 12V	31a	-	-
1N535	Si-Di	=1N530: 600V	34a	-	BA158..159, BY405, 1N4005..07, +

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1N5350	Z-Di	=1N5333:13V	31a	-	-
1N5351	Z-Di	=1N5333:14V	31a	-	-
1N5352	Z-Di	=1N5333:15V	31a	-	-
1N5353	Z-Di	=1N5333:16V	31a	-	-
1N5354	Z-Di	=1N5333:17V	31a	-	-
1N5355	Z-Di	=1N5333:18V	31a	-	-
1N5356	Z-Di	=1N5333:19V	31a	-	-
1N5357	Z-Di	=1N5333:20V	31a	-	-
1N5358	Z-Di	=1N5333:22V	31a	-	-
1N5359	Z-Di	=1N5333:24V	31a	-	-
1N536	Si-Di	Gl,50V,0,75A	34a	Rca,Tlx,++	BY126..127,BY133..135,1N4001..07,+
1N5360	Z-Di	=1N5333:25V	31a	-	-
1N5361	Z-Di	=1N5333:27V	31a	-	-
1N5362	Z-Di	=1N5333:28V	31a	-	-
1N5363	Z-Di	=1N5333:30V	31a	-	-
1N5364	Z-Di	=1N5333:33V	31a	-	-
1N5365	Z-Di	=1N5333:36V	31a	-	-
1N5366	Z-Di	=1N5333:39V	31a	-	-
1N5367	Z-Di	=1N5333:43V	31a	-	-
1N5368	Z-Di	=1N5333:47V	31a	-	-
1N5369	Z-Di	=1N5333:51V	31a	-	-
1N537	Si-Di	=1N536:100V	34a	-	BY126..127,BY133..135,1N4002..07,+
1N5370	Z-Di	=1N5333:56V	31a	-	-
1N5371	Z-Di	=1N5333:60V	31a	-	-
1N5372	Z-Di	=1N5333:62V	31a	-	-
1N5373	Z-Di	=1N5333:68V	31a	-	-
1N5374	Z-Di	=1N5333:75V	31a	-	-
1N5375	Z-Di	=1N5333:82V	31a	-	-
1N5376	Z-Di	=1N5333:87V	31a	-	-
1N5377	Z-Di	=1N5333:91V	31a	-	-
1N5378	Z-Di	=1N5333:100V	31a	-	-
1N5379	Z-Di	=1N5333:110V	31a	-	-
1N538	Si-Di	=1N536:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1N5380	Z-Di	=1N5333:120V	31a	-	-
1N5381	Z-Di	=1N5333:130V	31a	-	-
1N5382	Z-Di	=1N5333:140V	31a	-	-
1N5383	Z-Di	=1N5333:150V	31a	-	-
1N5384	Z-Di	=1N5333:160V	31a	-	-
1N5385	Z-Di	=1N5333:170V	31a	-	-
1N5386	Z-Di	=1N5333:180V	31a	-	-
1N5387	Z-Di	=1N5333:190V	31a	-	-
1N5388	Z-Di	=1N5333:200V	31a	-	-
1N5389	Si-Di	kV-Gl,40kV,200ns	31a	Edi	-
1N539	Si-Di	=1N536:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N5390	Si-Di	Schottky-Di,5V,<1pF,890MHz	31a	Fch,Tho	-
1N5391(A,GP)	Si-Di	Gl,50V,1,5A	31a	USA,Mot,Tho	BY251..255,BY226..227,BYW52..56,+
1N5392(A,GP)	Si-Di	=1N5391:100V	31a	-	BY251..255,BY226..227,BYW52..56,+
1N5393(A,GP)	Si-Di	=1N5391:200V	31a	-	BY251..255,BY226..227,BYW52..56,+
1N5394(A,GP)	Si-Di	=1N5391:300V	31a	-	BY252..255,BY226..227,BYW53..56,+
1N5395(A,GP)	Si-Di	=1N5391:400V	31a	-	BY252..255,BY226..227,BYW53..56,+
1N5396(A,GP)	Si-Di	=1N5391:500V	31a	-	BY253..255,BY226..227,BYW54..56,+
1N5397(A,GP)	Si-Di	=1N5391:600V	31a	-	BY253..255,BY226..227,BYW54..56,+
1N5398(A,GP)	Si-Di	=1N5391:800V	31a	-	BY254..255,BY227,BYW55..56,+
1N5399(A,GP)	Si-Di	=1N5391:1000V	31a	-	BY255,BY227,BYW56,GP15M,+
1N54(A)	Ge-Di	Uni,75V,50mA	31a	USA,Nec,Tho	AA113,AA117..118,1N34
1N540(S)	Si-Di	=1N536:400V	34a	-	BY126..127,BY133..134,1N4004..07,+
1N5400(K)	Si-Di	Gl,50V,3A,5?s	31a	USA,Mot,Tho	BY251..255,BYW17/100,BYW82,+
1N5401(K)	Si-Di	=1N5400:100V	31a	-	BY251..255,BYW17/100,BYW82,+
1N5402(K)	Si-Di	=1N5400:200V	31a	-	BY251..255,BYW17/200,BYW82,+
1N5403(K)	Si-Di	=1N5400:300V	31a	-	BY252..255,BYW17/400,BYW83,+
1N5404(K)	Si-Di	=1N5400:400V	31a	-	BY252..255,BYW17/400,BYW83,+
1N5405(K)	Si-Di	=1N5400:500V	31a	-	BY253..255,BYW17/600,BYW84,+
1N5406(K)	Si-Di	=1N5400:600V	31a	-	BY253..255,BYW17/600,BYW84,+
1N5407(K)	Si-Di	=1N5400:800V	31a	-	BY254..255,BYW17/800,BYW85,+

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1N5408(R)	Si-Di	=1N5400; 1000V	31a	-	BY255, BYW17/1000, BYW86, +
1N5409	Si-Di	Gl-L, 300V, 40A(Tc=100o)	32a$	USA	BYX97/300
1N541	Ge-Di	Dem, h-ohm, 50V, 30mA	31a	USA, Tho	AA113, AA119, 1N34, 1N54, 1N60
1N5410	Si-Di	Gl-L, 300V, 12A(Tc=100o)	32a$	USA	BYW88/300, BYX78..81, 1N4507..11, +
1N5411	Diac	Ub=29..35V, Ib<0,05mA, Itsm=2A	31	Rca	1N5761, N413M, BR100, D3202Y, DO201YR
1N5412	Si-Di	SS, 40V, 0,2A, <2pF(0V), <2ns	31a	Hit, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5413	Si-Di	=1N5412: 80V	31a	Hit, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5414	Si-Di	=1N5412: 100V	31a	Hit, Msc, Sem	BAW62, BAW76, BAX95, 1N4148..49, +
1N5415	Si-Di	Gl, 50V, 3A, <150ns	31a	USA, Gie, Tho	BYW16/100, BYW72..76, RGP30A, +
1N5416	Si-Di	=1N5415: 100V	31a	-	BYW16/100, BYW72..76, RGP30B, +
1N5417	Si-Di	=1N5415: 200V	31a	-	BYW16/200, BYW72..76, RGP30D, +
1N5418	Si-Di	=1N5415: 400V	31a	-	BYW16/400, BYW74..76, RGP30G, +
1N5419	Si-Di	=1N5415: 500V, <250ns	31a	-	BYW16/600, BYW76, RGP30K, +
1N542	Ge-Di	=1N541; gep	2x31a	-	AA113, AA119, 1N34, 1N54, 1N60
1N5420	Si-Di	=1N5415: 600V, <400ns	31a	-	BYW16/600, BYW76, RGP30K
1N5421	Si-Di	VHF-Tuning, 200V, 150pF(8V)	31a	Cod, Miv	-
1N5422	Si-Di	VHF-Tuning, 200V, 250pF(8V)	31a	Cod, Miv	-
1N5423	Si-Di	VHF-Tuning, 200V, 500pF(8V)	31a	Cod, Miv	-
1N5424	Si-Di	VHF-Tuning, 100V, 500pF(8V)	31a	Cod, Miv	-
1N5425	Si-Di	VHF-Tuning, 100V, 1000pF(8V)	31a	Cod, Miv	-
1N5426	Si-Di	25V, <1,1pF(0V)	-	Miv	-
1N5427	Si-Di	SS, RadH, 75V, <2pF, <4ns	31a	Fch	-
1N5428	Si-Di	S, RadH, 200V, <5pF, <50ns	31a	Fch	-
1N5429	Si-Di	RadH, 200V, <6pF	31a	Fch	-
1N543(A)	Si-Di	Gl, 1500V, 10mA, A: 35mA	34a	old	DMS13, EMS16, RGP01-16, SHG1,5
1N5430	Si-Di	SS, RadH, 75V, <2,5pF, <4ns	31a	Fch	-
1N5431	Si-Di	SS, RadH, 80V, <2,5pF, <4ns	31a	Fch	-
1N5432	Si-Di	SS, RadH, 20V, <1pF, <0,75ns	31a	Fch	-
1N5433	Si-Di	Gl, S, 720V, 2mA, <400ns	31a	Ssi, Trw	BA158..159, BY204/8, BY203/12, +
1N5434	Si-Di	Gl, S, 720V, 2mA, <400ns	31a	Ssi, Trw	BA158..159, BY204/8, BY203/12, +
1N5435	Si-Di	Gl/S-L, 720V, 12A(Tc=25o)	31a	Ssi, Trw	-
1N5436	Si-Di	UHF, Ku-Band-M, 12..18GHz	Koax	Miv, Sld	-
1N5437	Si-Di	UHF, Ku-Band-M, 12..18GHz	Koax	Miv, Sld	-
1N5438	Si-Di	UHF, Ku-Band-M, 12..18GHz	Koax	Miv, Sld	-
1N544(A)	Si-Di	Gl, 1200V, 15mA, A: 75mA	34a	old	DMS13, EMS16, RGP01-16, SHG1,5
1N5441(A..D)	Si-Di	A=n10%, B=n5%, C=n2%, D=n1%	-		-
1N5441(A..D)	Si-Di	FM/VHF-AFC/Tuning, 6,8pF(n20%)(4V)	31a	Mot, Tho, ++	-
1N5442(A..D)	Si-Di	=1N5441: 8,2pF(4V)	31a	Mot, Tho, ++	-
1N5443(A..D)	Si-Di	=1N5441: 10pF(4V)	31a	Mot, Tho, ++	-
1N5444(A..D)	Si-Di	=1N5441: 12pF(4V)	31a	Mot, Tho, ++	-
1N5445(A..D)	Si-Di	=1N5441: 15pF(4V)	31a	Mot, Tho, ++	-
1N5446(A..D)	Si-Di	=1N5441: 18pF(4V)	31a	Mot, Tho, ++	-
1N5447(A..D)	Si-Di	=1N5441: 20pF(4V)	31a	Mot, Tho, ++	-
1N5448(A..D)	Si-Di	=1N5441: 22pF(4V)	31a	Mot, Tho, ++	-
1N5449(A..D)	Si-Di	=1N5441: 27pF(4V)	31a	Mot, Tho, ++	-
1N5450(A..D)	Si-Di	=1N5441: 33pF(4V)	31a	Mot, Tho, ++	-
1N5451(A..D)	Si-Di	=1N5441: 39pF(4V)	31a	Mot, Tho, ++	-
1N5452(A..D)	Si-Di	=1N5441: 47pF(4V)	31a	Mot, Tho, ++	-
1N5453(A..D)	Si-Di	=1N5441: 56pF(4V)	31a	Mot, Tho, ++	-
1N5454(A..D)	Si-Di	=1N5441: 68pF(4V)	31a	Mot, Tho, ++	-
1N5455(A..D)	Si-Di	=1N5441: 82pF(4V)	31a	Mot, Tho, ++	-
1N5456(A..D)	Si-Di	=1N5441: 100pF(4V)	31a	Mot, Tho, ++	-
1N5461(A..D)	Si-Di	A=n10%, B=n5%, C=n2%, D=n1%	-		-
1N5461(A..D)	Si-Di	FM..UHF-AFC/Tuning, 6,8pF(4V)	31a	Mot, Miv, Tdy	-
1N5462(A..D)	Si-Di	=1N5461: 8,2pF(4V)	31a	Mot, Miv, Tdy	-
1N5463(A..D)	Si-Di	=1N5461: 10pF(4V)	31a	Mot, Miv, Tdy	-
1N5464(A..D)	Si-Di	=1N5461: 12pF(4V)	31a	Mot, Miv, Tdy	-
1N5465(A..D)	Si-Di	=1N5461: 15pF(4V)	31a	Mot, Miv, Tdy	-
1N5466(A..D)	Si-Di	=1N5461: 18pF(4V)	31a	Mot, Miv, Tdy	-
1N5467(A..D)	Si-Di	=1N5461: 20pF(4V)	31a	Mot, Miv, Tdy	-
1N5468(A..D)	Si-Di	=1N5461: 22pF(4V)	31a	Mot, Miv, Tdy	-
1N5469(A..D)	Si-Di	=1N5461: 27pF(4V)	31a	Mot, Miv, Tdy	-
1N547(S)	Si-Di	Gl, 600V, 0,75A	34a	Rca, Tix, ++	BY126..127, BY133..134, 1N4005, +
1N5470(A..D)	Si-Di	=1N5461: 33pF(4V)	31a	Mot, Miv, Tdy	-

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1N5471(A..D)	Si-Di	=1N5461:39pF(4V)	31a	Mot,Miv,Tdy	-
1N5472(A..D)	Si-Di	=1N5461:47pF(4V)	31a	Mot,Miv,Tdy	-
1N5473(A..D)	Si-Di	=1N5461:56pF(4V)	31a	Mot,Miv,Tdy	-
1N5474(A..D)	Si-Di	=1N5461:68pF(4V)	31a	Mot,Miv,Tdy	-
1N5475(A..D)	Si-Di	=1N5461:82pF(4V)	31a	Mot,Miv,Tdy	-
1N5476(A..D)	Si-Di	=1N5461:100pF(4V)	31a	Mot,Miv,Tdy	-
1N5477	Si-Di	kV-Gl,6kV,0,6A	-	USA	-
1N5478	Si-Di	=1N5477:7,2kV	-	USA	-
1N5479	Si-Di	=1N5477:8,4kV	-	USA	-
1N548	Si-Di	Gl,900V,0,3A	31a	old	BA159,BY127,BY133,1N4007,+
1N5480	Si-Di	=1N5477:9,6kV	-	USA	-
1N5481	Si-Di	=1N5477:12kV	-	USA	-
1N5482	Si-Di	kV-Gl,2,4kV,1A	31a	USA	-
1N5483	Si-Di	=1N5482:3,6kV	31a	USA	-
1N5484	Si-Di	=1N5482:4,8kV	31a	USA	-
1N5485	Si-Di	=1N5482:6kV	31a	USA	-
1N549	Si-Di	=1N548:1200V	31a	old	BY127,BY133,BYX95,EM513,+
1N55(A,B)	Ge-Di	Uni,150V,A:150V,50mA,B:180V,30mA	31a	USA,Tho	-
1N550	Si-Di	Gl-L,100V,0,5A	32a$	Sem,Tix,++	BYX38/300,BYX39/600
1N551	Si-Di	=1N550:200V	32a$	-	BYX38/300,BYX39/600
1N5510A...5546A	Z-Di	=1N5518..5546:10%	31a	-	-
1N5510A..5546A..	Z-Di	3,3..33V,0,4W,10%	31a	-	-
1N5510B...5546B	Z-Di	=1N5518..5546:5%	31a	-	-
1N5510B..5546B..	Z-Di	3,3..33V,0,4W,5%	31a	-	-
1N5510C...5546C..	Z-Di	=1N5518..5546:2%	31a	-	-
1N5510C..5546C...	Z-Di	3,3..33V,0,4W,2%	31a	-	-
1N5510D...5546D	Z-Di	=1N5518..5546:1%	31a	-	-
1N5510D..5546D..	Z-Di	3,3..33V,0,4W,1%	31a	-	-
1N5518	Z-Di	3,3V,20%,0,4W	31a	USA,Mot	BZX55/..,BZX55/..,ZPD..,1N5226..57,+
1N5518A..1N5546A	Z-Di	3,3..33V,0,4W,10%	31a	Mot	-
1N5518B..1N5546B..	Z-Di	3,3..33V,0,4W,5%	31a	Mot	-
1N5518C..1N5546C..	Z-Di	3,3..33V,0,4W,2%	31a	Mot	-
1N5518D..1N5546D	Z-Di	3,3..33V,0,4W,1%	31a	Mot	-
1N5519	Z-Di	=1N5518:3,6V	31a	-	-
1N552	Si-Di	=1N550:300V	32a$	-	BYX38/300,BYX39/600
1N5520	Z-Di	=1N5518:3,9V	31a	-	-
1N5521	Z-Di	=1N5518:4,3V	31a	-	-
1N5522	Z-Di	=1N5518:4,7V	31a	-	-
1N5523	Z-Di	=1N5518:5,1V	31a	-	-
1N5524	Z-Di	=1N5518:5,6V	31a	-	-
1N5525	Z-Di	=1N5518:6,2V	31a	-	-
1N5526	Z-Di	=1N5518:6,8V	31a	-	-
1N5527	Z-Di	=1N5518:7,5V	31a	-	-
1N5528	Z-Di	=1N5518:8,2V	31a	-	-
1N5529	Z-Di	=1N5518:9,1V	31a	-	-
1N553	Si-Di	=1N550:400V	32a$	-	BYX38/600,BYX39/600
1N5530	Z-Di	=1N5518:10V	31a	-	-
1N5531	Z-Di	=1N5518:11V	31a	-	-
1N5532	Z-Di	=1N5518:12V	31a	-	-
1N5533	Z-Di	=1N5518:13V	31a	-	-
1N5534	Z-Di	=1N5518:14V	31a	-	-
1N5535	Z-Di	=1N5518:15V	31a	-	-
1N5536	Z-Di	=1N5518:16V	31a	-	-
1N5537	Z-Di	=1N5518:17V	31a	-	-
1N5538	Z-Di	=1N5518:18V	31a	-	-
1N5539	Z-Di	=1N5518:19V	31a	-	-
1N554	Si-Di	=1N550:500V	32a$	-	BYX38/600,BYX39/600
1N5540	Z-Di	=1N5518:20V	31a	-	-
1N5541	Z-Di	=1N5518:22V	31a	-	-
1N5542	Z-Di	=1N5518:24V	31a	-	-
1N5543	Z-Di	=1N5518:25V	31a	-	-
1N5544	Z-Di	=1N5518:28V	31a	-	-
1N5545	Z-Di	=1N5518:30V	31a	-	-
1N5546	Z-Di	=1N5518:33V	31a	-	-

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1N555	Si-Di	=1N550:600V	32a$	-	BYX38/600,BYX39/600
1N5550	Si-Di	GI,S,200V,3A	31a	USA,Gie	BY251..255,BYW17/200,BYW82..86,+
1N5551	Si-Di	=1N5550:400V	31a	-	BY252..255,BYW17/400,BYW83..86,+
1N5552	Si-Di	=1N5550:600V	31a	-	BY253..255,BYW17/600,BYW84..86,+
1N5553	Si-Di	=1N5550:800V	31a	-	BY254..255,BYW17/800,BYW85..86,+
1N5554	Si-Di	=1N5550:1000V	31a	-	BY255,BYW17/1000,BYW86,1N5408,+
1N5555	Z-Di	TAZ,33V,1,5kW(1ms)	34a	USA,Sie	1N5645
1N5556	Z-Di	=1N5555:43,7V	34a	-	1N5648
1N5557	Z-Di	=1N5555:54V	34a	-	1N5651
1N5558	Z-Di	=1N5555:191V	34a	-	1N5664
1N5559	Z-Di	6,8V,20%,1W	31a	USA	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1N5559A..5594A	Z-Di	=1N5559..5594:10%	31a	-	-
1N5559A..5594A	Z-Di	=1N5559..5594:10%	31a	-	-
1N5559B..5594B	Z-Di	=1N5559..5594:5%	31a	-	-
1N5559B..5594B	Z-Di	=1N5559..5594:5%	31a	-	-
1N5560	Z-Di	=1N5559:7,5V	31a	-	-
1N5561	Z-Di	=1N5559:8,2V	31a	-	-
1N5562	Z-Di	=1N5559:9,1V	31a	-	-
1N5563	Z-Di	=1N5559:10V	31a	-	-
1N5564	Z-Di	=1N5559:11V	31a	-	-
1N5565	Z-Di	=1N5559:12V	31a	-	-
1N5566	Z-Di	=1N5559:13V	31a	-	-
1N5567	Z-Di	=1N5559:15V	31a	-	-
1N5568	Z-Di	=1N5559:16V	31a	-	-
1N5569	Z-Di	=1N5559:18V	31a	-	-
1N5570	Z-Di	=1N5559:20V	31a	-	-
1N5571	Z-Di	=1N5559:22V	31a	-	-
1N5572	Z-Di	=1N5559:24V	31a	-	-
1N5573	Z-Di	=1N5559:27V	31a	-	-
1N5574	Z-Di	=1N5559:30V	31a	-	-
1N5575	Z-Di	=1N5559:33V	31a	-	-
1N5576	Z-Di	=1N5559:36V	31a	-	-
1N5577	Z-Di	=1N5559:39V	31a	-	-
1N5578	Z-Di	=1N5559:43V	31a	-	-
1N5579	Z-Di	=1N5559:47V	31a	-	-
1N558	Si-Di	GI,1500V,15mA	34a	Tix	BAY91,RGP01-16,
1N5580	Z-Di	=1N5559:51V	31a	-	-
1N5581	Z-Di	=1N5559:56V	31a	-	-
1N5582	Z-Di	=1N5559:62V	31a	-	-
1N5583	Z-Di	=1N5559:68V	31a	-	-
1N5584	Z-Di	=1N5559:75V	31a	-	-
1N5585	Z-Di	=1N5559:82V	31a	-	-
1N5586	Z-Di	=1N5559:91V	31a	-	-
1N5587	Z-Di	=1N5559:100V	31a	-	-
1N5588	Z-Di	=1N5559:110V	31a	-	-
1N5589	Z-Di	=1N5559:120V	31a	-	-
1N5590	Z-Di	=1N5559:130V	31a	-	-
1N5591	Z-Di	=1N5559:150V	31a	-	-
1N5592	Z-Di	=1N5559:160V	31a	-	-
1N5593	Z-Di	=1N5559:180V	31a	-	-
1N5594	Z-Di	=1N5559:200V	31a	-	-
1N5595	Si-Di	kV-GI,5kV,1,15A(Tc=100o)	-	USA	-
1N5596	Si-Di	kV-GI,7,5kV,0,87A(Tc=100o)	-	USA	-
1N5597	Si-Di	kV-GI,10kV,0,7A(Tc=100o)	-	USA	-
1N5598	Si-Di	kV-GI,15kV,0,47A(Tc=100o)	-	USA	-
1N5599	Si-Di	kV-GI,2,5kV,2,1A(Tc=100o)	-	USA	-
1N56(A)	Ge-Di	Uni,50V,60mA,A:46V,0,8pF	31a	USA,Tho	AA117..118,AA132..134,1N60
1N560	Si-Di	GI,800V,0,25A	34a	Sem,Tix,++	BY127,BY133,BYW42,G1K,1N4006,+
1N5600	Si-Di	kV-GI,5kV,1,4A(Tc=100o)	-	USA	-
1N5601	Si-Di	kV-GI,7,5kV,0,92A(Tc=100o)	-	USA	-
1N5602	Si-Di	kV-GI,2,5kV,4,6A(Tc=100o)	-	USA	-
1N5603	Si-Di	kV-GI,5kV,3,5A(Tc=100o)	-	USA	-
1N5604	Si-Di	kV-GI,7,5kV,2,3A(Tc=100o)	-	USA	-
1N5605	Si-Di	Uni,70V,<8pF(0V)	31a	USA,Itt	BA188..190,BAY19..21,BAY45..46,+

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1N5606	Si-Di	Uni,150V,0,1A,<6pF(0V)	31a	USA,Itt	BA189..190,BAY20..21,BAY45..46,+
1N5607	Si-Di	Uni,200V,0,15A,<4pF(0V)	31a	USA,Itt	BA190,BAW52,BAY21,BAY46,+
1N5608	Si-Di	S,120V,0,15A,<300ns	31a	USA,Hit,Itt	BA157..159,BAV19..21,BAX15..17,+
1N5609	Si-Di	S,120V,0,15A,<2,7pF(0V),<300ns	31a	USA,Hit,Itt	BA157..159,BAV19..21,BAX15..17,+
1N561	Si-Di	=1N560:1000V	34a	-	BY127,BY133,BYW43,G1M,1N4007,+
1N5610	Z-Di	=1N5555:	31a	Uni	→1N5555
1N5611	Z-Di	=1N5556:	31a	Uni	→1N5556
1N5612	Z-Di	=1N5557:	31a	Uni	→1N5557
1N5613	Z-Di	=1N5558:	31a	-	→1N5558
1N5614	Si-Di	Gl,200V,1A,20pF(12V),<2?s	31a	USA,Sie,Tho	BY126..127,BY133..134,1N4003..07,+
1N5615	Si-Di	-	31a	Sie,Tho	BY201/2,BYT52D,BYX92/200..
1N5615(GP)	Si-Di	Gl,S,200V,1A,20pF(12V),<150ns	31a	USA,Sie,Tho	BY201/2,BYT52D,BYX92/200,+
1N5616	Si-Di	=1N5614:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1N5617	Si-Di	=1N5615:400V	31a	-	BY201/4,BYT52G,BYX92/400,+
1N5618	Si-Di	=1N5614:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1N5619	Si-Di	=1N5615:600V,<250ns	31a	-	BY201/6,BYT52J,RGP10J,+
1N562	Si-Di	Gl-L,800V,0,4A	32a$	USA	BYX38/900,BYX39/800
1N5620	Si-Di	=1N5614:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1N5620P1..5665P1	Z-Di		=1N5629..5665:31a		
1N5621	Si-Di	=1N5615:800V,<300ns	31a	-	BYV15..16,BYT52K,RGP10K,+
1N5622	Si-Di	=1N5614:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1N5623	Si-Di	=1N5615:1000V	31a	-	BYV16,BYV36E,BYT52M,RGP10M,+
1N5624(GP)	Si-Di	Gl,200V,5A,30pF(4V),3?s	31a	USA,EUR,Nec	BY500-200,MR752..760,MR822..826
1N5625(GP)	Si-Di	=1N5624:400V	31a	-	BY500-400,MR754..760,MR824..826
1N5626(GP)	Si-Di	=1N5624:600V	31a	-	BY500-600,MR756..760,MR826
1N5627(GP)	Si-Di	=1N5624:800V	31a	-	BY500-800,MR758..760
1N5628	Si-Di	kV-Gl,3kV,0,5A	-	Gen	-
1N5629(A)	Z-Di	TAZ,6,8V,1,5kW(1ms)	34a	USA,Sie,Tho	1N6267..6303,(1N6036..72,1N6138..73)
1N563	Si-Di	=1N562:1000V	32a$	-	BYX38/1200,BYX39/1000
1N5630(A)	Z-Di	=1N5629:7,5V	34a	-	-
1N5631(A)	Z-Di	=1N5629:8,2V	34a	-	-
1N5632(A)	Z-Di	=1N5629:9,1V	34a	-	-
1N5633(A)	Z-Di	=1N5629:10V	34a	-	-
1N5634(A)	Z-Di	=1N5629:11V	34a	-	-
1N5635(A)	Z-Di	=1N5629:12V	34a	-	-
1N5636(A)	Z-Di	=1N5629:13V	34a	-	-
1N5637(A)	Z-Di	=1N5629:15V	34a	-	-
1N5638(A)	Z-Di	=1N5629:16V	34a	-	-
1N5639(A)	Z-Di	=1N5629:18V	34a	-	-
1N5640(A)	Z-Di	=1N5629:20V	34a	-	-
1N5641(A)	Z-Di	=1N5629:22V	34a	-	-
1N5642(A)	Z-Di	=1N5629:24V	34a	-	-
1N5643(A)	Z-Di	=1N5629:27V	34a	-	-
1N5644(A)	Z-Di	=1N5629:30V	34a	-	-
1N5645(A)	Z-Di	=1N5629:33V	34a	-	-
1N5646(A)	Z-Di	=1N5629:36V	34a	-	-
1N5647(A)	Z-Di	=1N5629:39V	34a	-	-
1N5648(A)	Z-Di	=1N5629:43V	34a	-	-
1N5649(A)	Z-Di	=1N5629:47V	34a	-	-
1N5650(A)	Z-Di	=1N5629:51V	34a	-	-
1N5651(A)	Z-Di	=1N5629:56V	34a	-	-
1N5652(A)	Z-Di	=1N5629:62V	34a	-	-
1N5653(A)	Z-Di	=1N5629:68V	34a	-	-
1N5654(A)	Z-Di	=1N5629:75V	34a	-	-
1N5655(A)	Z-Di	=1N5629:82V	34a	-	-
1N5656(A)	Z-Di	=1N5629:91V	34a	-	-
1N5657(A)	Z-Di	=1N5629:100V	34a	-	-
1N5658(A)	Z-Di	=1N5629:110V	34a	-	-
1N5659(A)	Z-Di	=1N5629:120V	34a	-	-
1N566	Ge-Di	Uni,275V	31a	kdc	-
1N5660(A)	Z-Di	=1N5629:130V	34a	-	-
1N5661(A)	Z-Di	=1N5629:150V	34a	-	-
1N5662(A)	Z-Di	=1N5629:160V	34a	-	-
1N5663(A)	Z-Di	=1N5629:170V	34a	-	-

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1N5664(A)	Z-Di	=1N5629:180V	34a	-	-
1N5665(A)	Z-Di	=1N5629:200V	34a	-	-
1N5666	Z-Di	1,6V,20%,0,25W	2	Sie,Sty	BZX55/..,BZX79/..,ZPD..,1N5221..32,+
1N5666A...5678A	Z-Di	=1N5666..5678:10%	2	-	-
1N5666A..5678A	Z-Di	=1N5666..5678:10%	2	-	-
1N5667	Z-Di	=1N5666:1,8V	2	-	-
1N5668	Z-Di	=1N5666:2V	2	-	-
1N5669	Z-Di	=1N5666:2,2V	2	-	-
1N567	Ge-Di	S,125V,300ns	31a	Idc,Sem	-
1N5670	Z-Di	=1N5666:2,5V	2	-	-
1N5671	Z-Di	=1N5666:2,8V	2	-	-
1N5672	Z-Di	=1N5666:3,1V	2	-	-
1N5673	Z-Di	=1N5666:3,4V	2	-	-
1N5674	Z-Di	=1N5666:3,7V	2	-	-
1N5675	Z-Di	=1N5666:4,1V	2	-	-
1N5676	Z-Di	=1N5666:4,5V	2	-	-
1N5677	Z-Di	=1N5666:4,9V	2	-	-
1N5678	Z-Di	=1N5666:5,4V	2	-	-
1N5679	Si-Di	Gl,50V,1A	31a	Gie	BY126..127,BY133..135,1N4001..07,+
1N568	Ge-Di	S,50V,80ns	31a	Idc,Itt,Sem	-
1N5680	Si-Di	=1N5679:100V	31a	-	BY126..127,BY133..135,1N4001..07,+
1N5681(A,B)	Si-Di	A=n10%,B=n5%	-		-
1N5681(A,B)	Si-Di	VHF-Tuning,6,8pF(n20%)(4V)	31a	Cod,Trw	-
1N5682(A,B)	Si-Di	=1N5681:8,2pF(4V)	31a	Cod,Trw	-
1N5683(A,B)	Si-Di	=1N5681:10pF(4V)	31a	Cod,Trw	-
1N5684(A,B)	Si-Di	=1N5681:12pF(4V)	31a	Cod,Trw	-
1N5685(A,B)	Si-Di	=1N5681:15pF(4V)	31a	Cod,Trw	-
1N5686(A,B)	Si-Di	=1N5681:18pF(4V)	31a	Cod,Trw	-
1N5687(A,B)	Si-Di	=1N5681:22pF(4V)	31a	Cod,Trw	-
1N5688(A,B)	Si-Di	=1N5681:27pF(4V)	31a	Cod,Trw	-
1N5689(A,B)	Si-Di	=1N5681:33pF(4V)	31a	Cod,Trw	-
1N569	Ge-Di	Uni,25V	31a	Idc,Itt,Sem	AA139,1N270
1N5690(A,B)	Si-Di	=1N5681:39pF(4V)	31a	Cod,Trw	-
1N5691(A,B)	Si-Di	=1N5681:47pF(4V)	31a	Cod,Trw	-
1N5692(A,B)	Si-Di	=1N5681:56pF(4V)	31a	Cod,Trw	-
1N5693(A,B)	Si-Di	=1N5681:68pF(4V)	31a	Cod,Trw	-
1N5694(A,B)	Si-Di	=1N5681:82pF(4V)	31a	Cod,Trw	-
1N5695(A,B)	Si-Di	=1N5681:100pF(4V)	31a	Cod,Trw	-
1N5696(A,B)	Si-Di	A=±10%,B=±5%	-		-
1N5696(A,B)	Si-Di	VHF-Tuning,6,8pF(n20%)(4V)	31a	Cod,Trw	-
1N5697(A,B)	Si-Di	=1N5696:8,2pF(4V)	31a	Cod,Trw	-
1N5698(A,B)	Si-Di	=1N5696:10pF(4V)	31a	Cod,Trw	-
1N5699(A,B)	Si-Di	=1N5696:12pF(4V)	31a	Cod,Trw	-
1N57(A)	Ge-Di	Uni,80V,40mA	31a	USA,Tho	AA117..118,AA132..133
1N570	Si-Di	Gl,1500V,0,75A	-	USA	-
1N5700(A,B)	Si-Di	=1N5696:15pF(4V)	31a	Cod,Trw	-
1N5701(A,B)	Si-Di	=1N5696:18pF(4V)	31a	Cod,Trw	-
1N5702(A,B)	Si-Di	=1N5696:22pF(4V)	31a	Cod,Trw	-
1N5703(A,B)	Si-Di	=1N5696:27pF(4V)	31a	Cod,Trw	-
1N5704(A,B)	Si-Di	=1N5696:33pF(4V)	31a	Cod,Trw	-
1N5705(A,B)	Si-Di	=1N5696:39pF(4V)	31a	Cod,Trw	-
1N5706(A,B)	Si-Di	=1N5696:47pF(4V)	31a	Cod,Trw	-
1N5707(A,B)	Si-Di	=1N5696:56pF(4V)	31a	Cod,Trw	-
1N5708(A,B)	Si-Di	=1N5696:68pF(4V)	31a	Cod,Trw	-
1N5709(A,B)	Si-Di	=1N5696:82pF(4V)	31a	Cod,Trw	-
1N571	Ge-Di	S,15V,<4?	34a	USA,Itt	-
1N5710(A,B)	Si-Di	=1N5696:100pF(4V)	31a	Cod,Trw	-
1N5711	Si-Di	Schottky,VHF/UHF-Dem,70V,15mA,<2pF	31a	USA,Tho	BAR28,HSS102
1N5712	Si-Di	Schottky,VHF/UHF-Dem,20V,35mA	31a	USA,Tho	BAR10,1S1992,1SS101,1SS109
1N5713	Si-Di	Schottky,12V,1,2pF(0V)	31a	USA	-
1N5714	Si-Di	VHF-Tuning,200V,150pF(8V)	31a	Tdy	-
1N5715	Si-Di	=1N5714:250pF(8V)	31a	Tdy	-
1N5716	Si-Di	=1N5714:500pF(8V)	31a	Tdy	-
1N5717	Si-Di	VHF-Tuning,100V,500pF(8V)	31a	Tdy	-

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1N5718	Si-Di	VHF-Tuning, 100V, 1000pF(8V)	31a	Tdy	-
1N5719	Si-Di	Uni, 100V, <0,25pF(100V)	31a	Hew, Mic	BA188..190, BA147/100, 1N5606..09, +
1N5720	Si-Di	S, 30V, <6pF(0V), <10ns	31a	Itt, Hit	BA317, BAW53, BAY71, 1N4148..49, +
1N5721	Si-Di	=1N5720: 15V	31a	Itt, Hit	BA317, BAW53, BAY71, 1N4148..49, +
1N5726	Si-Di	S, 60V, <6pF(0V), <10ns	31a	Itt, Hit	BAV14, BAW26..27
1N5727	Si-Di	=1N5726: 50V	31a	Itt, Hit	BAV14, BAW24..27
1N5728	Z-Di	4,7V, 0,4W	31a	USA, Phi, Sie	BZX55/.., BZX79/.., ZPD.., 1N5230..67, +
1N5728A..5757A	Z-Di	=1N5728..5757: 5%	31a	-	-
1N5728A..5757A..	Z-Di	=1N5728..5757: 5%	31a	-	-
1N5728B..5757B	Z-Di	=1N5728..5757: 2%	31a	-	-
1N5728B..5757B..	Z-Di	=1N5728..5757: 2%	31a	-	-
1N5728C..5757C..	Z-Di	=1N5728..5757: 1%	31a	-	-
1N5728C..5757C...	Z-Di	=1N5728..5757: 1%	31a	-	-
1N5729	Z-Di	=1N5728: 5,1V	31a	-	-
1N573	Ge-Di	Gl, 380V, 0,25A	-		-
1N5730	Z-Di	=1N5728: 5,6V	31a	-	-
1N5731	Z-Di	=1N5728: 6,2V	31a	-	-
1N5732	Z-Di	=1N5728: 6,8V	31a	-	-
1N5733	Z-Di	=1N5728: 7,5V	31a	-	-
1N5734	Z-Di	=1N5728: 8,2V	31a	-	-
1N5735	Z-Di	=1N5728: 9,1V	31a	-	-
1N5736	Z-Di	=1N5728: 10V	31a	-	-
1N5737	Z-Di	=1N5728: 11V	31a	-	-
1N5738	Z-Di	=1N5728: 12V	31a	-	-
1N5739	Z-Di	=1N5728: 13V	31a	-	-
1N574	Ge-Di	Gl, 380V, 0,3A	-		-
1N5740	Z-Di	=1N5728: 15V	31a	-	-
1N5741	Z-Di	=1N5728: 16V	31a	-	-
1N5742	Z-Di	=1N5728: 18V	31a	-	-
1N5743	Z-Di	=1N5728: 20V	31a	-	-
1N5744	Z-Di	=1N5728: 22V	31a	-	-
1N5745	Z-Di	=1N5728: 24V	31a	-	-
1N5746	Z-Di	=1N5728: 27V	31a	-	-
1N5747	Z-Di	=1N5728: 30V	31a	-	-
1N5748	Z-Di	=1N5728: 33V	31a	-	-
1N5749	Z-Di	=1N5728: 36V	31a	-	-
1N575(A)	Ge-Di	Gl, 380V, 0,35A	-		-
1N5750	Z-Di	=1N5728: 39V	31a	-	-
1N5751	Z-Di	=1N5728: 43V	31a	-	-
1N5752	Z-Di	=1N5728: 47V	31a	-	-
1N5753	Z-Di	=1N5728: 51V	31a	-	-
1N5754	Z-Di	=1N5728: 56V	31a	-	-
1N5755	Z-Di	=1N5728: 62V	31a	-	-
1N5756	Z-Di	=1N5728: 68V	31a	-	-
1N5757	Z-Di	=1N5728: 75V	31a	-	-
1N5758	Diac	Ub=16..24V, Ib<0,1mA, Itsm=2A	7	Mot	-
1N5758A	Diac	Ub=18..22V, Ib<0,025mA, Itsm=2A	7	Mot	-
1N5759	Diac	Ub=20..28V, Ib<0,1mA, Itsm=2A	7	Mot	-
1N5759A	Diac	Ub=22..26V, Ib<0,025mA, Itsm=2A	7	Mot	-
1N576(A)	Ge-Di	Gl, 380V, 0,4A	-		-
1N5760	Diac	Ub=24..32V, Ib<0,1mA, Itsm=2A	7	Mot	N413L, D3202U
1N5760A	Diac	Ub=26..30V, Ib<0,025mA, Itsm=2A	7	Mot	(N413L, D3202U)
1N5761	Diac	Ub=28..36V, Ib<0,1mA, Itsm=2A	7	Mot	N413M, BR100, D3202Y, D0201YR
1N5761A	Diac	Ub=30..34V, Ib<0,025mA, Itsm=2A	7	Mot	(N413M, BR100, D3202Y, D0201YR)
1N5762	Diac	Ub=32..40V, Ib<0,1mA, Itsm=2A	7	Mot	N413N, D3202U
1N5762A	Diac	Ub=34..38V, Ib<0,025mA, Itsm=2A	7	Mot	(N413N, D3202U)
1N5763	Si-Di	Gl-L, 26V, 300A(Tc=100o)	-	Del	-
1N5764	GaAs-Di	UHF, Ku-Band-M, 15..17GHz	Koax	Miv	-
1N5765	LED	~=4.8mm I=1mcd Uf=1.6V If=20mA	T046	Hpa	-
1N5766	Si-Di	Gl, S, 110V, <250pF, <400ns	32a$	Sol	1N4525..4530
1N5767	PIN-Di	Uni, 100V, <0,4pF(50V)	31a	Uni	-
1N5768	Si-Di	8-Di Logik-Gatter/logic gate	10-FLP	Fch	-
1N5770	Si-Di	8-Di Logik-Gatter/logic gate	10-FLP	Fch	-
1N5772	Si-Di	16-Di Logik-Gatter/logic gate	10-FLP	Fch	-

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1N5774	Si-Di	16-Di-Logik-Gatter/logicgate	14-FLP	Fch	-
1N5779	Trigger-Di	=1N5158: Ub=11..13V	31a	Mot	-
1N5780	Trigger-Di	=1N5158: Ub=12..14V	31a	Mot	-
1N5781	Trigger-Di	=1N5158: Ub=13..15V	31a	Mot	-
1N5782	Trigger-Di	=1N5158: Ub=8..10V, Ib<0,1mA	31a	Mot	-
1N5783	Trigger-Di	=1N5158: Ub=9..11V, Ib<0,1mA	31a	Mot	-
1N5784	Trigger-Di	=1N5158: Ub=10..12V, Ib<0,1mA	31a	Mot	-
1N5785	Trigger-Di	=1N5158: Ub=11..13V, Ib<0,1mA	31a	Mot	-
1N5786	Trigger-Di	=1N5158: Ub=12..14V, Ib<0,1mA	31a	Mot	-
1N5787	Trigger-Di	=1N5158: Ub=13..15V, Ib<0,1mA	31a	Mot	-
1N5788	Trigger-Di	=1N5158: Ub=8..10V, Ib<0,1mA	31a	Mot	-
1N5789	Trigger-Di	=1N5158: Ub=9..11V, Ib<0,1mA	31a	Mot	-
1N5790	Trigger-Di	=1N5158: Ub=10..12V, Ib<0,1mA	31a	Mot	-
1N5791	Trigger-Di	=1N5158: Ub=11..13V, Ib<0,1mA	31a	Mot	-
1N5792	Trigger-Di	=1N5158: Ub=12..14V, Ib<0,1mA	31a	Mot	-
1N5793	Trigger-Di	=1N5158: Ub=13..15V, Ib<0,1mA	31a	Mot	-
1N5794	Si-Di	Gl, 50V, 1A	31a	Fch	BY126..127, BY133..135, 1N4001..07, +
1N5795	Si-Di	=1N5794: 100V	31a	-	BY126..127, BY133..135, 1N4002..07, +
1N5796	Si-Di	=1N5794: 200V	31a	-	BY126..127, BY133..134, 1N4003..07, +
1N5797	Si-Di	=1N5794: 400V	31a	-	BY126..127, BY133..134, 1N4004..07, +
1N5798	Si-Di	=1N5794: 600V	31a	-	BY126..127, BY133..134, 1N4005..07, +
1N5799	Si-Di	=1N5794: 800V	31a	-	BY127, BY133, BY227, 1N4006..07, +
1N58(A)	Ge-Di	Uni, 115V, 50mA, A: 120V	31a	USA, Nec, Tho	AA117..118, AA132..133
1N5800	Si-Di	=1N5794: 1000V	31a	-	BY127, BY133, BY227, 1N4007, +
1N5802	Si-Di	Gl, S, 50V, 2,5A, 15pF(10V), <25ns	31a	USA, Gie	BYV28/50, EGP30A, FE3A
1N5803	Si-Di	=1N5802: 75V	31a	-	BYV28/100, EGP30B, FE3B
1N5804	Si-Di	=1N5802: 100V	31a	-	BYV28/100, EGP30B, FE3B
1N5805	Si-Di	=1N5802: 125V	31a	-	BYV28/150, EGP30C, FE3C
1N5806	Si-Di	=1N5802: 150V	31a	-	BYV28/150, EGP30C, FE3C
1N5807	Si-Di	Gl, S, 50V, 6A, <35pF(10V), <30ns	31a	USA, Gie	BYV61..63, FE6A
1N5808	Si-Di	=1N5807: 75V	31a	-	BYV62..63, FE6B
1N5809	Si-Di	=1N5807: 100V	31a	-	BYV62..63, FE6B
1N581	Ge-Di	Gl, 380V, 0,25A	-	Gen	-
1N5810	Si-Di	=1N5807: 125V	31a	-	BYV63, FE6C
1N5811	Si-Di	=1N5807: 150V	31a	-	BYV63, FE6C
1N5812	Si-Di	Gl/S-L, 50V, 20A, 200pF(10V), <25ns	32a$	USA, Gie	BYW77/50
1N5813	Si-Di	=1N5812: 75V	32a$	-	BYW77/100
1N5814	Si-Di	=1N5812: 100V	32a$	-	BYW77/100
1N5815	Si-Di	=1N5812: 125V	32a$	-	BYW77/150
1N5816	Si-Di	=1N5812: 150V	32a$	-	BYW77/150
1N5817	Si-Di	Schottky-Gl, 20V, 1A, Uf<0,45V(1A)	31a	Gie, Mot, Phl	BYS21, BYV10-20, SB120
1N5818	Si-Di	=1N5817: 30V, Uf<0,55V(1A)	31a	-	BYS21, BYV10-30, SB130
1N5819	Si-Di	=1N5817: 40V, Uf<0,6V(1A)	31a	-	BYS21, BYV10-40, SB140
1N582	Ge-Di	Gl, 380V, 0,3A	-	Gen	-
1N5820	Si-Di	Schottky-Gl, 20V, 3A, Uf<0,475V(3A)	31a	Gie, Mot	BYS26, MBR320, SB320
1N5821	Si-Di	=1N5820: 30V, Uf<0,5V(3A)	31a	Gie, Mot	BYS26, MBR330, SB330
1N5822	Si-Di	=1N5820: 40V, Uf<0,525V(3A)	31a	Gie, Mot	BYS26, MBR340, SB340, HRP24
1N5823	Si-Di	Schottky-Gl, 20V, 5A, Uf<0,47V(15,7A)	34a	Mot	BYS08, SB520
1N5824	Si-Di	=1N5823: 30V, Uf<0,49V(15,7A)	34a	-	BYS08, SB530
1N5825	Si-Di	=1N5823: 40V, Uf<0,52(15,7A)	34a	-	BYS08, SB540
1N5826	Si-Di	Schottky, 20V, 15A(Tc=85o), Uf<0,44V	32a$	Mot	BYS15, MBR1520
1N5827	Si-Di	=1N5826: 30V, Uf<0,47V(15A)	32a$	-	BYS15, MBR1530
1N5828	Si-Di	=1N5826: 40V, Uf<0,5V(15A)	32a$	-	BYS15, MBR1540
1N5829	Si-Di	Schottky, 20V, 25A(Tc=85o), Uf<0,44V	32a$	Mot	BYS30..32, BYS35/20, MBR2520
1N583	Ge-Di	Gl, 380V, 0,35A	-	Gen	-
1N5830	Si-Di	=1N5829: 30V, Uf<0,46(25A)	32a$	-	BYS30..32, BYS35/30, MBR2530
1N5831	Si-Di	=1N5829: 40V, Uf<0,48V(25A)	32a$	-	BYS30..32, BYS35/40, MBR2540
1N5832	Si-Di	Schottky, 20V, 40A(Tc=75o), Uf<0,52V	32a$	Mot	BYS50..51, BYS60/20, MBR4020
1N5833	Si-Di	=1N5832: 30V, Uf<0,55V(40A)	32a$	-	BYS50..51, BYS60/30, MBR4030
1N5834	Si-Di	=1N5832: 40V, Uf<0,59V(40A)	32a$	-	BYS50..51, BYS60/40, MBR4040
1N5835	Si-Di	Gl, S, 30V, 3A, <100ns	31a	Cri	BYV28/50, EGP30A, FE3A
1N5836	Si-Di	=1N5835: 50V	31a	-	BYV28/50, EGP30A, FE3A
1N5837	Z-Di	2,4V, 20%, 0,5W	7d	Fer, Mot, Spr	BZX55/.., BZX83/.., ZPD.., 1N5221..81, +
1N5837A...5897A	Z-Di	=1N5837..5897: 10%	7d	-	-

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1N5837A..5897A..	Z-Di	=1N5837..5897:10%	7d	-	-
1N5837B...5897B .	Z-Di	=1N5837..5897:5%	7d	-	-
1N5837B..5897B ..	Z-Di	=1N5837..5897:5%	7d	-	-
1N5837C...5897C..	Z-Di	=1N5837..5897:2%	7d	-	-
1N5837C.5897C...	Z-Di	=1N5837..5897:2%	7d	-	-
1N5837D..5897D .	Z-Di	=1N5837..5897:1%	7d	-	-
1N5837D..5897D ..	Z-Di	=1N5837..5897:1%	7d	-	-
1N5838	Z-Di	=1N5837:2,5V	7d	-	-
1N5839	Z-Di	=1N5837:2,7V	7d	-	-
1N584	Ge-Di	Gl,380V,0,4A	-	Gen	-
1N5840	Z-Di	=1N5837:2,8V	7d	-	-
1N5841	Z-Di	=1N5837:3V	7d	-	-
1N5842	Z-Di	=1N5837:3,3V	7d	-	-
1N5843	Z-Di	=1N5837:3,6V	7d	-	-
1N5844	Z-Di	=1N5837:3,9V	7d	-	-
1N5845	Z-Di	=1N5837:4,3V	7d	-	-
1N5846	Z-Di	=1N5837:4,7V	7d	-	-
1N5847	Z-Di	=1N5837:5,1V	7d	-	-
1N5848	Z-Di	=1N5837:5,6V	7d	-	-
1N5849	Z-Di	=1N5837:6V	7d	-	-
1N5850	Z-Di	=1N5837:6,2V	7d	-	-
1N5851	Z-Di	=1N5837:6,8V	7d	-	-
1N5852	Z-Di	=1N5837:7,5V	7d	-	-
1N5853	Z-Di	=1N5837:8,2V	7d	-	-
1N5854	Z-Di	=1N5837:8,7V	7d	-	-
1N5855	Z-Di	=1N5837:9,1V	7d	-	-
1N5856	Z-Di	=1N5837:10V	7d	-	-
1N5857	Z-Di	=1N5837:11V	7d	-	-
1N5858	Z-Di	=1N5837:12V	7d	-	-
1N5859	Z-Di	=1N5837:13V	7d	-	-
1N5860	Z-Di	=1N5837:14V	7d	-	-
1N5861	Z-Di	=1N5837:15V	7d	-	-
1N5862	Z-Di	=1N5837:16V	7d	-	-
1N5863	Z-Di	=1N5837:17V	7d	-	-
1N5864	Z-Di	=1N5837:18V	7d	-	-
1N5865	Z-Di	=1N5837:19V	7d	-	-
1N5866	Z-Di	=1N5837:20V	7d	-	-
1N5867	Z-Di	=1N5837:22V	7d	-	-
1N5868	Z-Di	=1N5837:24V	7d	-	-
1N5869	Z-Di	=1N5837:25V	7d	-	-
1N5870	Z-Di	=1N5837:27V	7d	-	-
1N5871	Z-Di	=1N5837:28V	7d	-	-
1N5872	Z-Di	=1N5837:30V	7d	-	-
1N5873	Z-Di	=1N5837:33V	7d	-	-
1N5874	Z-Di	=1N5837:36V	7d	-	-
1N5875	Z-Di	=1N5837:39V	7d	-	-
1N5876	Z-Di	=1N5837:43V	7d	-	-
1N5877	Z-Di	=1N5837:47V	7d	-	-
1N5878	Z-Di	=1N5837:51V	7d	-	-
1N5879	Z-Di	=1N5837:56V	7d	-	-
1N588	Si-Di	Gl,1500V,0,1A	34a	USA	BAY91,RGP01-16
1N5880	Z-Di	=1N5837:60V	7d	-	-
1N5881	Z-Di	=1N5837:62V	7d	-	-
1N5882	Z-Di	=1N5837:68V	7d	-	-
1N5883	Z-Di	=1N5837:75V	7d	-	-
1N5884	Z-Di	=1N5837:82V	7d	-	-
1N5885	Z-Di	=1N5837:87V	7d	-	-
1N5886	Z-Di	=1N5837:91V	7d	-	-
1N5887	Z-Di	=1N5837:100V	7d	-	-
1N5888	Z-Di	=1N5837:110V	7d	-	-
1N5889	Z-Di	=1N5837:120V	7d	-	-
1N589	Si-Di	Gl,1500V,0,25A	34a	USA	BAY91,DM513,EM516,GP10Y
1N5890	Z-Di	=1N5837:130V	7d	-	-
1N5891	Z-Di	=1N5837:140V	7d	-	-

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1N5892	Z-Di	=1N5837:150V	7d	-	-
1N5893	Z-Di	=1N5837:160V	7d	-	-
1N5894	Z-Di	=1N5837:170V	7d	-	-
1N5895	Z-Di	=1N5837:180V	7d	-	-
1N5896	Z-Di	=1N5837:190V	7d	-	-
1N5897	Z-Di	=1N5837:200V	7d	-	-
1N5898	Si-Di	GI,S,50V,3A,<S?s	-	Gie	BY251..255,BYW17/100,1N5400..08,+
1N5899	Si-Di	=1N5898:100V	-		BY251..255,BYW17/100,1N5401..08,+
1N59	Ge-Di	Uni,280V,50mA	31a	Idc	-
1N590	Si-Di	GI,1500V,25mA	?34a	Ssi	BAY91,RGP01-16
1N5900	Si-Di	=1N5898:200V	-		BY251..255,BYW17/200,1N5402..08,+
1N5901	Si-Di	=1N5898:400V	-		BY252..255,BYW17/400,1N5404..08,+
1N5902	Si-Di	=1N5898:600V	-		BY253..255,BYW17/600,1N5406..08,+
1N5903	Si-Di	=1N5898:800V	-		BY254..255,BYW17/800,1N5407..08,+
1N5904	Si-Di	=1N5898:1000V	-		BY255,BYW17/1000,1N5408,+
1N5905	Si-Di	=1N5898:1200V	-		BY255,BY438,BYW17/1200
1N5906	Si-Di	UHF,Ku-Band-M,15..17GHz	Koax	Mlv	-
1N5907	Z-Di	=1N5629:6...7V	34a	Scn,Sie,Tho	-
1N5908	Z-Di	=1N5629:6...7V	31a	-	-
1N5909...5912	Opto	-	-	-	-
1N591	Si-Di	=1N590:	?34b	-	BAY91,RGP01-16
1N5913	Z-Di	3,3V,20%,1,5W(Tc=75o)	31a	USA,Mot,Sie	BZW22/..,BZX61/..,ZPY..,BZY97/..
1N5913A...5956A	Z-Di	=1N5913..5956:10%	31a	-	-
1N5913A..5956A	Z-Di	=1N5913..5956:10%	31a	-	-
1N5913B...5956B	Z-Di	=1N5913..5956:5%	31a	-	-
1N5913B..5956B	Z-Di	=1N5913..5956:5%	31a	-	-
1N5913C...5956C	Z-Di	=1N5913..5956:2%	31a	-	-
1N5913C..5956C	Z-Di	=1N5913..5956:2%	31a	-	-
1N5913D...5956D	Z-Di	=1N5913..5956:1%	31a	-	-
1N5913D..5956D	Z-Di	=1N5913..5956:1%	31a	-	-
1N5914	Z-Di	=1N5913:3,6V	31a	-	-
1N5915	Z-Di	=1N5913:3,9V	31a	-	-
1N5916	Z-Di	=1N5913:4,3V	31a	-	-
1N5917	Z-Di	=1N5913:4,7V	31a	-	-
1N5918	Z-Di	=1N5913:5,1V	31a	-	-
1N5919	Z-Di	=1N5913:5,6V	31a	-	-
1N5920	Z-Di	=1N5913:6,2V	31a	-	-
1N5921	Z-Di	=1N5913:6,8V	31a	-	-
1N5922	Z-Di	=1N5913:7,5V	31a	-	-
1N5923	Z-Di	=1N5913:8,2V	31a	-	-
1N5924	Z-Di	=1N5913:9,1V	31a	-	-
1N5925	Z-Di	=1N5913:10V	31a	-	-
1N5926	Z-Di	=1N5913:11V	31a	-	-
1N5927	Z-Di	=1N5913:12V	31a	-	-
1N5928	Z-Di	=1N5913:13V	31a	-	-
1N5929	Z-Di	=1N5913:15V	31a	-	-
1N5930	Z-Di	=1N5913:16V	31a	-	-
1N5931	Z-Di	=1N5913:18V	31a	-	-
1N5932	Z-Di	=1N5913:20V	31a	-	-
1N5933	Z-Di	=1N5913:22V	31a	-	-
1N5934	Z-Di	=1N5913:24V	31a	-	-
1N5935	Z-Di	=1N5913:27V	31a	-	-
1N5936	Z-Di	=1N5913:30V	31a	-	-
1N5937	Z-Di	=1N5913:33V	31a	-	-
1N5938	Z-Di	=1N5913:36V	31a	-	-
1N5939	Z-Di	=1N5913:39V	31a	-	-
1N5940	Z-Di	=1N5913:43V	31a	-	-
1N5941	Z-Di	=1N5913:47V	31a	-	-
1N5942	Z-Di	=1N5913:51V	31a	-	-
1N5943	Z-Di	=1N5913:56V	31a	-	-
1N5944	Z-Di	=1N5913:62V	31a	-	-
1N5945	Z-Di	=1N5913:68V	31a	-	-
1N5946	Z-Di	=1N5913:75V	31a	-	-
1N5947	Z-Di	=1N5913:82V	31a	-	-

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1N5948	Z-Di	=1N5913:91V	31a	-	-
1N5949	Z-Di	=1N5913:100V	31a	-	-
1N5950	Z-Di	=1N5913:110V	31a	-	-
1N5951	Z-Di	=1N5913:120V	31a	-	-
1N5952	Z-Di	=1N5913:130V	31a	-	-
1N5953	Z-Di	=1N5913:150V	31a	-	-
1N5954	Z-Di	=1N5913:160V	31a	-	-
1N5955	Z-Di	=1N5913:180V	31a	-	-
1N5956	Z-Di	=1N5913:200V	31a	-	-
1N5957	PIN-Di	100V,<0,4pF(50V),Rs<3,5e(100mA)	31a	Uni	-
1N596	Si-Di	Gl,600V,0,15A	34a	USA	BA158..159,BAY89..90,BY207
1N5968	Z-Di	5,6V,5%,5W	31a	Uni	BZV40/C5V6,BZV48/C5V6,2N5339B
1N5969	Z-Di	6,2V,5%,5W	31a	Uni	BZV40/C6V2,BZV48/C6V2,2N5341B
1N597	Si-Di	=1N596:800V	34a	-	BA159,BAY90,BY204/8
1N598	Si-Di	=1N596:1000V	34a	-	BA159,BAY90,BY204/10
1N5985	Z-Di	2,4V,20%,0,5W	31a	USA,Mot,Sie	BZX55/..,BZX83/..,ZPD..,1N5221..B1,..
1N5985A...6031A	Z-Di	=1N5985..6031:10%	31a	-	-
1N5985A..6031A..	Z-Di	=1N5985..6031:10%	31a	-	-
1N5985B	Z-Di	2.4V,0.5W,Zzt=100Ω	-	Fairchild	-
1N5985B...6031B	Z-Di	=1N5985..6031:5%	31a	-	-
1N5985B..6031B..	Z-Di	=1N5985..6031:5%	31a	-	-
1N5985C...6031C..	Z-Di	=1N5985..6031:2%	31a	-	-
1N5985C..6031C...	Z-Di	=1N5985..6031:2%	31a	-	-
1N5985D...6031D	Z-Di	=1N5985..6031:1%	31a	-	-
1N5985D..6031D..	Z-Di	=1N5985..6031:1%	31a	-	-
1N5986	Z-Di	=1N5985:2,7V	31a	-	-
1N5986B	Z-Di	2.7V,0.5W,Zzt=100Ω	-	Fairchild	-
1N5987	Z-Di	=1N5985:3V	31a	-	-
1N5987B	Z-Di	3V,0.5W,Zzt=95Ω	-	Fairchild	-
1N5988	Z-Di	=1N5985:3,3V	31a	-	-
1N5988B	Z-Di	3.3V,0.5W,Zzt=95Ω	-	Fairchild	-
1N5989	Z-Di	=1N5985:3,6V	31a	-	-
1N5989B	Z-Di	3.6V,0.5W,Zzt=90Ω	-	Fairchild	-
1N599(A)	Si-Di	Gl,50V,0,4A	34a	USA,Tlx	BA157..159,BY401..405,1N4001..07,+
1N5990	Z-Di	=1N5985:3,9V	31a	-	-
1N5990B	Z-Di	3.9V,0.5W,Zzt=90Ω	-	Fairchild	-
1N5991	Z-Di	=1N5985:4,3V	31a	-	-
1N5991B	Z-Di	4.3V,0.5W,Zzt=80Ω	-	Fairchild	-
1N5992	Z-Di	=1N5985:4,7V	31a	-	-
1N5992B	Z-Di	4.7V,0.5W,Zzt=70Ω	-	Fairchild	-
1N5993	Z-Di	=1N5985:5,1V	31a	-	-
1N5993B	Z-Di	5.1V,0.5W,Zzt=50Ω	-	Fairchild	-
1N5994	Z-Di	=1N5985:5,6V	31a	-	-
1N5994B	Z-Di	5.6V,0.5W,Zzt=25Ω	-	Fairchild	-
1N5995	Z-Di	=1N5985:6,2V	31a	-	-
1N5995B	Z-Di	6.2V,0.5W,Zzt=10Ω	-	Fairchild	-
1N5996	Z-Di	=1N5985:6,8V	31a	-	-
1N5996B	Z-Di	6.8V,0.5W,Zzt=8Ω	-	Fairchild	-
1N5997	Z-Di	=1N5985:7,5V	31a	-	-
1N5997B	Z-Di	7.5V,0.5W,Zzt=7Ω	-	Fairchild	-
1N5998	Z-Di	=1N5985:8,2V	31a	-	-
1N5998B	Z-Di	8.2V,0.5W,Zzt=7Ω	-	Fairchild	-
1N5999	Z-Di	=1N5985:9,1V	31a	-	-
1N5999B	Z-Di	9.1V,0.5W,Zzt=10Ω	-	Fairchild	-
1N60(A)	Ge-Di	AM/FM-Dem,TV-ZF-Dem,50V,50mA	31a	USA,EUR,JAP	AA113,AA138,1N34,1N54
1N600(A)	Si-Di	=1N599:100V	34a	-	BA157..159,BY402..405,1N4002..07,+
1N6000	Z-Di	=1N5985:10V	31a	-	-
1N6000B	Z-Di	10V,0.5W,Zzt=15Ω	-	Fairchild	-
1N6001	Z-Di	=1N5985:11V	31a	-	-
1N6001B	Z-Di	11V,0.5W,Zzt=18Ω	-	Fairchild	-
1N6002	Z-Di	=1N5985:12V	31a	-	-
1N6002B	Z-Di	12V,0.5W,Zzt=22Ω	-	Fairchild	-
1N6003	Z-Di	=1N5985:13V	31a	-	-
1N6003B	Z-Di	13V,0.5W,Zzt=25Ω	-	Fairchild	-

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1N6004	Z-Di	=1N5985; 15V	31a	-	-
1N6004B	Z-Di	15V, 0.5W, Zzt=32Ω	-	Fairchild	-
1N6005	Z-Di	=1N5985: 16V	31a	-	-
1N6005B	Z-Di	16V, 0.5W, Zzt=36Ω	-	Fairchild	-
1N6006	Z-Di	=1N5985: 18V	31a	-	-
1N6006B	Z-Di	18V, 0.5W, Zzt=42Ω	-	Fairchild	-
1N6007	Z-Di	=1N5985: 20V	31a	-	-
1N6007B	Z-Di	20V, 0.5W, Zzt=48Ω	-	Fairchild	-
1N6008	Z-Di	=1N5985: 22V	31a	-	-
1N6008B	Z-Di	22V, 0.5W, Zzt=55Ω	-	Fairchild	-
1N6009	Z-Di	=1N5985: 24V	31a	-	-
1N6009B	Z-Di	24V, 0.5W, Zzt=62Ω	-	Fairchild	-
1N601(A)	Si-Di	=1N599: 150V	34a	-	BA157..159, BY403..405, 1N4003..07, +
1N6010	Z-Di	=1N5985: 27V	31a	-	-
1N6010B	Z-Di	27V, 0.5W, Zzt=70Ω	-	Fairchild	-
1N6011	Z-Di	=1N5985: 30V	31a	-	-
1N6011B	Z-Di	30V, 0.5W, Zzt=70Ω	-	Fairchild	-
1N6012	Z-Di	=1N5985: 33V	31a	-	-
1N6012B	Z-Di	33V, 0.5W, Zzt=88Ω	-	Fairchild	-
1N6013	Z-Di	=1N5985: 36V	31a	-	-
1N6013B	Z-Di	36V, 0.5W, Zzt=95Ω	-	Fairchild	-
1N6014	Z-Di	=1N5985: 39V	31a	-	-
1N6014B	Z-Di	39V, 0.5W, Zzt=130Ω	-	Fairchild	-
1N6015	Z-Di	=1N5985: 43V	31a	-	-
1N6015B	Z-Di	43V, 0.5W, Zzt=150Ω	-	Fairchild	-
1N6016	Z-Di	=1N5985: 47V	31a	-	-
1N6016B	Z-Di	47V, 0.5W, Zzt=170Ω	-	Fairchild	-
1N6017	Z-Di	=1N5985: 51V	31a	-	-
1N6017B	Z-Di	51V, 0.5W, Zzt=180Ω	-	Fairchild	-
1N6018	Z-Di	=1N5985: 56V	31a	-	-
1N6018B	Z-Di	56V, 0.5W, Zzt=200Ω	-	Fairchild	-
1N6019	Z-Di	=1N5985: 62V	31a	-	-
1N6019B	Z-Di	62V, 0.5W, Zzt=225Ω	-	Fairchild	-
1N602(A)	Si-Di	=1N599: 200V	34a	-	BA157..159, BY403..405, 1N4003..07, +
1N6020	Z-Di	=1N5985: 68V	31a	-	-
1N6020B	Z-Di	68V, 0.5W, Zzt=240Ω	-	Fairchild	-
1N6021	Z-Di	=1N5985: 75V	31a	-	-
1N6021B	Z-Di	75V, 0.5W, Zzt=265Ω	-	Fairchild	-
1N6022	Z-Di	=1N5985: 82V	31a	-	-
1N6022B	Z-Di	82V, 0.5W, Zzt=280Ω	-	Fairchild	-
1N6023	Z-Di	=1N5985: 91V	31a	-	-
1N6023B	Z-Di	91V, 0.5W, Zzt=300Ω	-	Fairchild	-
1N6024	Z-Di	=1N5985: 100V	31a	-	-
1N6024B	Z-Di	100V, 0.5W, Zzt=500Ω	-	Fairchild	-
1N6025	Z-Di	=1N5985: 110V	31a	-	-
1N6025B	Z-Di	110V, 0.5W, Zzt=650Ω	-	Fairchild	-
1N6026	Z-Di	=1N5985: 120V	31a	-	-
1N6027	Z-Di	=1N5985: 130V	31a	-	-
1N6028	Z-Di	=1N5985: 150V	31a	-	-
1N6029	Z-Di	=1N5985: 160V	31a	-	-
1N603(A)	Si-Di	=1N599: 300V	34a	-	BA157..159, BY404..405, 1N4004..07, +
1N6030	Z-Di	=1N5985: 180V	31a	-	-
1N6031	Z-Di	=1N5985: 200V	31a	-	-
1N6036(A)	Z-Di	=1N5630: bidirektional/bi-polarity	34a	USA, Tho	1N6138..6173
1N6037(A)	Z-Di	=1N5631: bidirektional/bi-polarity	34a	-	-
1N6038(A)	Z-Di	=1N5632: bidirektional/bi-polarity	34a	-	-
1N6039(A)	Z-Di	=1N5633: bidirektional/bi-polarity	34a	-	-
1N604(A)	Si-Di	=1N599: 400V	34a	-	BA157..159, BY404..405, 1N4004..07, +
1N6040(A)	Z-Di	=1N5634: bidirektional/bi-polarity	34a	-	-
1N6041(A)	Z-Di	=1N5635: bidirektional/bi-polarity	34a	-	-
1N6042(A)	Z-Di	=1N5636: bidirektional/bi-polarity	34a	-	-
1N6043(A)	Z-Di	=1N5637: bidirektional/bi-polarity	34a	-	-
1N6044(A)	Z-Di	=1N5638: bidirektional/bi-polarity	34a	-	-
1N6045(A)	Z-Di	=1N5639: bidirektional/bi-polarity	34a	-	-

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1N6046(A)	Z-Di	=1N5640:bidirektional/bi-polarity	34a	-	-
1N6047(A)	Z-Di	=1N5641:bidirektional/bi-polarity	34a	-	-
1N6048(A)	Z-Di	=1N5642:bidirektional/bi-polarity	34a	-	-
1N6049(A)	Z-Di	=1N5643:bidirektional/bi-polarity	34a	-	-
1N605(A)	Si-Di	=1N599:500V	34a	-	BA158..159,BY405,1N4005..07,+
1N6050(A)	Z-Di	=1N5644:bidirektional/bi-polarity	34a	-	-
1N6051(A)	Z-Di	=1N5645:bidirektional/bi-polarity	34a	-	-
1N6052(A)	Z-Di	=1N5646:bidirektional/bi-polarity	34a	-	-
1N6053(A)	Z-Di	=1N5647:bidirektional/bi-polarity	34a	-	-
1N6054(A)	Z-Di	=1N5648:bidirektional/bi-polarity	34a	-	-
1N6055(A)	Z-Di	=1N5649:bidirektional/bi-polarity	34a	-	-
1N6056(A)	Z-Di	=1N5650:bidirektional/bi-polarity	34a	-	-
1N6057(A)	Z-Di	=1N5651:bidirektional/bi-polarity	34a	-	-
1N6058(A)	Z-Di	=1N5652:bidirektional/bi-polarity	34a	-	-
1N6059(A)	Z-Di	=1N5653:bidirektional/bi-polarity	34a	-	-
1N606(A)	Si-Di	=1N599:600V	34a	-	BA158..159,BY405,1N4005..07,+
1N6060(A)	Z-Di	=1N5654:bidirektional/bi-polarity	34a	-	-
1N6061(A)	Z-Di	=1N5655:bidirektional/bi-polarity	34a	-	-
1N6062(A)	Z-Di	=1N5656:bidirektional/bi-polarity	34a	-	-
1N6063(A)	Z-Di	=1N5657:bidirektional/bi-polarity	34a	-	-
1N6064(A)	Z-Di	=1N5658:bidirektional/bi-polarity	34a	-	-
1N6065(A)	Z-Di	=1N5659:bidirektional/bi-polarity	34a	-	-
1N6066(A)	Z-Di	=1N5660:bidirektional/bi-polarity	34a	-	-
1N6067(A)	Z-Di	=1N5661:bidirektional/bi-polarity	34a	-	-
1N6068(A)	Z-Di	=1N5662:bidirektional/bi-polarity	34a	-	-
1N6069(A)	Z-Di	=1N5663:bidirektional/bi-polarity	34a	-	-
1N607(A)	Si-Di	Gl-L,50V,1A	32a$	USA,Tix	BYX38/300,BYX39/600
1N6070(A)	Z-Di	=1N5664:bidirektional/bi-polarity	34a	-	-
1N6071(A)	Z-Di	=1N5665:bidirektional/bi-polarity	34a	-	-
1N6072(A)	Z-Di	=1N5665:220V,bidirektional/bi-pol	34a	-	-
1N6073	Si-Di	Gl,S,50V,3A,200pF,30ns	31a	Msc,Smt	BYV28/50,EGP30A,FE3A
1N6074	Si-Di	=1N6073:100V,100pF	31a	-	BYV28/100,EGP30B,FE3B
1N6075	Si-Di	=1N6073:150V,24pF	31a	-	BYV28/150,EGP30C,FE3C
1N6076	Si-Di	Gl,S,50V,6A,300pF,30ns	31a	Msc,Smt	BYV61..63,FE6A
1N6077	Si-Di	=1N6076:100V,200pF	31a	-	BYV61..63,FE6A
1N6078	Si-Di	=1N6076:150V,150pF	31a	-	BYV61..63,FE6A
1N6079	Si-Di	Gl,S,50V,12A,600pF,30ns	31a	Msc,Smt	-
1N607R...614R	Si-Di	=1N607(A)..614(A):	32b&	-	BYX38/600R,BYX39/600R
1N607R..614R	Si-Di	-	32b&	-	BYX38/600R,BYX39/600R
1N608(A)	Si-Di	=1N607(A):100V	32a$	-	BYX38/300,BYX39/600
1N6080	Si-Di	=1N6079:100V,380pF	31a	-	-
1N6081	Si-Di	=1N6079:150V	31a	-	-
1N6082	Z-Di	4,3V,20%,0,4W	31a	Ksw,Msc,Trw	BZX55/..,BZX79/..,ZPD..,1N5229..40,+
1N6082A...6091A	Z-Di	=1N6082..6091:10%	31a	-	-
1N6082A..6091A..	Z-Di	=1N6082..6091:10%	31a	-	-
1N6082B...6091B	Z-Di	=1N6082..6091:5%	31a	-	-
1N6082B..6091B..	Z-Di	=1N6082..6091:5%	31a	-	-
1N6082C...6091C..	Z-Di	=1N6082..6091:2%	31a	-	-
1N6082C..6091C...	Z-Di	=1N6082..6091:2%	31a	-	-
1N6082D...6091D	Z-Di	=1N6082..6091:1%	31a	-	-
1N6082D..6091D..	Z-Di	=1N6082..6091:1%	31a	-	-
1N6083	Z-Di	=1N6082:4,7V	31a	-	-
1N6084	Z-Di	=1N6082:5,1V	31a	-	-
1N6085	Z-Di	=1N6082:5,6V	31a	-	-
1N6086	Z-Di	=1N6082:6,2V	31a	-	-
1N6087	Z-Di	=1N6082:6,8V	31a	-	-
1N6088	Z-Di	=1N6082:7,5V	31a	-	-
1N6089	Z-Di	=1N6082:8,2V	31a	-	-
1N609(A)	Si-Di	=1N607(A):150V	32a$	-	BYX38/300,BYX39/600
1N6090	Z-Di	=1N6082:9,1V	31a	-	-
1N6091	Z-Di	=1N6082:10V	31a	-	-
1N6092	LED	~=4.8mm I=8mcd Uf=2V If=20mA	T046	Hpa	-
1N6093	LED	~=4.8mm I=8mcd Uf=2.1V If=20mA	T046	Hpa	-
1N6094	LED	~=4.8mm I=8mcd Uf=2.1V If=20mA	-	Hpa	-

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1N6095	Si-Di	Schottky-Gl,30V,25A(Tc=70o),Uf<0,86V	32a$	USA,Inr,Mot	BYS30..32,BYV121/35,MBR2530
1N6096	Si-Di	=1N6095:40V	32a$	-	BYS30..32,BYV121/40,MBR2540
1N6097	Si-Di	Schottky-Gl,30V,50A(Tc=70o),Uf<0,86V	32a$	USA,Inr,Mot	BYS50..51,BYS60/30,MBR6030
1N6098	Si-Di	=1N6098:40V	32a$	-	BYS50..51,BYS60/40,MBR6045
1N6099	Si-Di	=1N3595	31a	Fch	→1N3595
1N61	Ge-Di	Uni,140V,40mA	31a	USA	AA133,1N39
1N610(A)	Si-Di	=1N607(A):200V	32a$	-	BYX38/300,BYX39/600
1N6100	Si-Di	7-Di Array,65V,0,35A,<15ns	14-FLP	Fch	-
1N6101	Si-Di	=1N6100:	14-DIP	-	-
1N6102(A)	Z-Di	TAZ,bidirektional,6,8V,500W(1ms)	31a	USA,Gle,Tho	BZW06/..B
1N6103(A)	Z-Di	=1N6102:7,5V	31a	-	-
1N6104(A)	Z-Di	=1N6102:8,2V	31a	-	-
1N6105(A)	Z-Di	=1N6102:9,1V	31a	-	-
1N6106(A)	Z-Di	=1N6102:10V	31a	-	-
1N6107(A)	Z-Di	=1N6102:11V	31a	-	-
1N6108(A)	Z-Di	=1N6102:12V	31a	-	-
1N6109(A)	Z-Di	=1N6102:13V	31a	-	-
1N611(A)	Si-Di	=1N607(A):300V	32a$	-	BYX38/300,BYX39/600
1N6110(A)	Z-Di	=1N6102:15V	31a	-	-
1N6111(A)	Z-Di	=1N6102:16V	31a	-	-
1N6112(A)	Z-Di	=1N6102:18V	31a	-	-
1N6113(A)	Z-Di	=1N6102:20V	31a	-	-
1N6114(A)	Z-Di	=1N6102:22V	31a	-	-
1N6115(A)	Z-Di	=1N6102:24V	31a	-	-
1N6116(A)	Z-Di	=1N6102:27V	31a	-	-
1N6117(A)	Z-Di	=1N6102:30V	31a	-	-
1N6118(A)	Z-Di	=1N6102:33V	31a	-	-
1N6119(A)	Z-Di	=1N6102:36V	31a	-	-
1N612(A)	Si-Di	=1N607(A):400V	32a$	-	BYX38/600,BYX39/600
1N6120(A)	Z-Di	=1N6102:39V	31a	-	-
1N6121(A)	Z-Di	=1N6102:43V	31a	-	-
1N6122(A)	Z-Di	=1N6102:47V	31a	-	-
1N6123(A)	Z-Di	=1N6102:51V	31a	-	-
1N6124(A)	Z-Di	=1N6102:56V	31a	-	-
1N6125(A)	Z-Di	=1N6102:62V	31a	-	-
1N6126(A)	Z-Di	=1N6102:68V	31a	-	-
1N6127(A)	Z-Di	=1N6102:75V	31a	-	-
1N6128(A)	Z-Di	=1N6102:82V	31a	-	-
1N6129(A)	Z-Di	=1N6102:91V	31a	-	-
1N613(A)	Si-Di	=1N607(A):500V	32a$	-	BYX38/600,BYX39/600
1N6130(A)	Z-Di	=1N6102:100V	31a	-	-
1N6131(A)	Z-Di	=1N6102:110V	31a	-	-
1N6132(A)	Z-Di	=1N6102:120V	31a	-	-
1N6133(A)	Z-Di	=1N6102:130V	31a	-	-
1N6134(A)	Z-Di	=1N6102:150V	31a	-	-
1N6135(A)	Z-Di	=1N6102:160V	31a	-	-
1N6136(A)	Z-Di	=1N6102:180V	31a	-	-
1N6137(A)	Z-Di	=1N6102:200V	31a	-	-
1N6138(A)	Z-Di	TAZ,bidirektional,6,8V,1,5kW	31a	USA,Tho	1N6036..6072
1N6139(A)	Z-Di	=1N6138:7,5V	31a	-	-
1N614(A)	Si-Di	=1N607(A):600V	32a$	-	BYX38/600,BYX39/600
1N6140(A)	Z-Di	=1N6138:8,2V	31a	-	-
1N6141(A)	Z-Di	=1N6138:9,1V	31a	-	-
1N6142(A)	Z-Di	=1N6138:10V	31a	-	-
1N6143(A)	Z-Di	=1N6138:11V	31a	-	-
1N6144(A)	Z-Di	=1N6138:12V	31a	-	-
1N6145(A)	Z-Di	=1N6138:13V	31a	-	-
1N6146(A)	Z-Di	=1N6138:15V	31a	-	-
1N6147(A)	Z-Di	=1N6138:16V	31a	-	-
1N6148(A)	Z-Di	=1N6138:18V	31a	-	-
1N6149(A)	Z-Di	=1N6138:20V	31a	-	-
1N615	Ge-Di	Uni,300V,75mA	31a	USA	-
1N6150(A)	Z-Di	=1N6138:22V	31a	-	-
1N6151(A)	Z-Di	=1N6138:24V	31a	-	-

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1N6152(A)	Z-Di	=1N6138:27V	31a	-	-
1N6153(A)	Z-Di	=1N6138:30V	31a	-	-
1N6154(A)	Z-Di	=1N6138:33V	31a	-	-
1N6155(A)	Z-Di	=1N6138:36V	31a	-	-
1N6156(A)	Z-Di	=1N6138:39V	31a	-	-
1N6157(A)	Z-Di	=1N6138:43V	31a	-	-
1N6158(A)	Z-Di	=1N6138:47V	31a	-	-
1N6159(A)	Z-Di	=1N6138:51V	31a	-	-
1N616	Ge-Di	Dem,30V,30mA,1pF(0V)	31a	USA	AA113..114,AA116,AA119,1N60,+
1N6160(A)	Z-Di	=1N6138:56V	31a	-	-
1N6161(A)	Z-Di	=1N6138:62V	31a	-	-
1N6162(A)	Z-Di	=1N6138:68V	31a	-	-
1N6163(A)	Z-Di	=1N6138:75V	31a	-	-
1N6164(A)	Z-Di	=1N6138:82V	31a	-	-
1N6165(A)	Z-Di	=1N6138:91V	31a	-	-
1N6166(A)	Z-Di	=1N6138:100V	31a	-	-
1N6167(A)	Z-Di	=1N6138:110V	31a	-	-
1N6168(A)	Z-Di	=1N6138:120V	31a	-	-
1N6169(A)	Z-Di	=1N6138:130V	31a	-	-
1N617	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N6170(A)	Z-Di	=1N6138:150V	31a	-	-
1N6171(A)	Z-Di	=1N6138:160V	31a	-	-
1N6172(A)	Z-Di	=1N6138:180V	31a	-	-
1N6173(A)	Z-Di	=1N6138:200V	31a	-	-
1N618	Ge-Di	Uni,90V,50mA	31a	USA	AA117..118,AA132..133
1N619	Si-Di	Uni,30V	31a	USA	BA127..128,BA222,BA147/50,1N4148+
1N61A1	Si-Di	=1N44A1:30kV	-	Tos	-
1N62	Ge-Di	Uni,140V,40mA	31a	USA	AA133,1N39
1N622	Si-Di	Uni,150V	31a	USA	BA147/150,1N5195..96,1N5606..07,+
1N625(A)	Si-Di	S,30V,20mA,<1000ns,A:<500ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N626(A)	Si-Di	=1N625:50V	31a	-	BA195,BAW49,BAX15..17,1N3070,+
1N6262	Si-Di	Gl-L,200V,85A(Tc=100o)	32a$	Sie	-
1N6263	Si-Di	Schottky-Di,VHF/UHF-Dem,60V,15mA	31a	Hew,Itt,Tho	BAR28,HSS100,HSS102
1N6264	IRED	945nm?=4.7mmI=8mcdUf=1.4V	T018	Har,Qtc,Rca	-
1N6266	IRED	945nm?=4.7mmI>25mW/SrUf<1.7V	T018	Har,Qtc,Rca	-
1N6267(A)	Z-Di	=1N5629:	31a	Gsi,Mot,Fag	(1N6036..6072,1N6138..6173)
1N6268(A)	Z-Di	=1N5630:	31a	-	-
1N6269(A)	Z-Di	=1N5631:	31a	-	-
1N627(A)	Si-Di	=1N625:100V	31a	-	BA195,BAW49,BAX15..17,1N3070,+
1N6270(A)	Z-Di	=1N5632:	31a	-	-
1N6271(A)	Z-Di	=1N5633:	31a	-	-
1N6272(A)	Z-Di	=1N5634:	31a	-	-
1N6273(A)	Z-Di	=1N5635:	31a	-	-
1N6274(A)	Z-Di	=1N5636:	31a	-	-
1N6275(A)	Z-Di	=1N5637:	31a	-	-
1N6276(A)	Z-Di	=1N5638:	31a	-	-
1N6277(A)	Z-Di	=1N5639:	31a	-	-
1N6278(A)	Z-Di	=1N5640:	31a	-	-
1N6279(A)	Z-Di	=1N5641:	31a	-	-
1N628(A)	Si-Di	=1N625:150V	31a	-	BA195,BAW50,BAX15..17,1N3070,+
1N6280(A)	Z-Di	=1N5642:	31a	-	-
1N6281(A)	Z-Di	=1N5643:	31a	-	-
1N6282(A)	Z-Di	=1N5644:	31a	-	-
1N6283(A)	Z-Di	=1N5645:	31a	-	-
1N6284(A)	Z-Di	=1N5646:	31a	-	-
1N6285(A)	Z-Di	=1N5647:	31a	-	-
1N6286(A)	Z-Di	=1N5648:	31a	-	-
1N6287(A)	Z-Di	=1N5649:	31a	-	-
1N6288(A)	Z-Di	=1N5650:	31a	-	-
1N6289(A)	Z-Di	=1N5651:	31a	-	-
1N629(A)	Si-Di	=1N625:200V	31a	-	BA195,BA197,BAW50,BAX17,+
1N6290(A)	Z-Di	=1N5652:	31a	-	-
1N6291(A)	Z-Di	=1N5653:	31a	-	-
1N6292(A)	Z-Di	=1N5654:	31a	-	-

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1N6293(A)	Z-Di	=1N5655:	31a	-	-
1N6294(A)	Z-Di	=1N5656:	31a	-	-
1N6295(A)	Z-Di	=1N5657:	31a	-	-
1N6296(A)	Z-Di	=1N5658:	31a	-	-
1N6297(A)	Z-Di	=1N5659:	31a	-	-
1N6298(A)	Z-Di	=1N5660:	31a	-	-
1N6299(A)	Z-Di	=1N5661:	31a	-	-
1N63(A)	Ge-Di	Uni, 100V, 50mA, A: 30mA	31a	USA, Tho	AA117..118, AA132..133
1N630(A)	Si-Di	UHF, L/X-Band-Dem, 6750MHz	Koax	Mlv, Syl	-
1N6300(A)	Z-Di	=1N5662:	31a	-	-
1N6301(A)	Z-Di	=1N5663:	31a	-	-
1N6302(A)	Z-Di	=1N5664:	31a	-	-
1N6303(A)	Z-Di	=1N5665:	31a	-	-
1N6304	Si-Di	Gl/S-L, 50V, 70A(Tc=100o), <50ns	32a$	Uni	BYW07/50, BYW08/50, BYW94/50
1N6304R..6306R	Si-Di	=1N6304..6306:	32b&	Uni	BYW07/..R
1N6305	Si-Di	=1N6304: 100V	32a$	Uni	BYW07/100, BYW08/100, BYW94/100
1N6306	Si-Di	=1N6304: 150V	32a$	Uni	BYW07/150, BYW08/150, BYW94/150
1N6307	Si-Di	40V, <2,5pF(0V)	31a	Hew	-
1N631	Ge-Di	S, 60V, 60mA, <300ns	31a	USA	AAY28, 1N276
1N632	Ge-Di	S, 60V, <300ns	31a	USA	AAY28, 1N276
1N633	Ge-Di	S, 90V, 60mA, <300ns	31a	USA	AAY28, 1N276
1N634	Ge-Di	Uni, 125V, 100mA	31a	USA	-
1N635	Ge-Di	Uni, 175V, 150mA	31a	USA	-
1N636	Ge-Di	Uni, 50V, 30mA	31a	USA	AA117..118, AA132..134, 1N34, 1N54, +
1N6373	Z-Di	TAZ, 5V, 1,5kW	31a	Mot	1N5629..49, 1N6267..6387
1N6374	Z-Di	=1N6373: 8V	31a	-	-
1N6375	Z-Di	=1N6373: 10V	31a	-	-
1N6376	Z-Di	=1N6373: 12V	31a	-	-
1N6377	Z-Di	=1N6373: 15V	31a	-	-
1N6378	Z-Di	=1N6373: 18V	31a	-	-
1N6379	Z-Di	=1N6373: 22V	31a	-	-
1N6380	Z-Di	=1N6373: 36V	31a	-	-
1N6381	Z-Di	=1N6373: 45V	31a	-	-
1N6382..6389	Z-Di	=1N6373..6381: bidirektional	31a	-	1N6036..55, 1N6138..58
1N6391	Si-Di	Schottky, 45V, 25A(Tc=125o), Uf<0,68V	32a$	Uni	BYS31-.., BYS32, BYV121-45
1N6392	Si-Di	Schottky, 45V, 60A(Tc=115o), Uf<0,68V	32a$	Uni	BYS50, BYS32-45, MBR6045
1N64(A)	Ge-Di	Uni, 25V, 50mA	31a	USA, Tho	AA113, AA119, 1N34, 1N54, 1N60, +
1N643(A)	Si-Di	S, 200V, 0,04A, 3pF, <300ns	31a	Fch, Tix, ++	BA195, BA197..198, BAW50, BAX17, +
1N645	Si-Di	-	-	-	-
1N645(A,B,GP)	Si-Di	-	31a	Gl, Tix, ++	BA157..159, BY206..207, BY404..405, +
1N645(A,B,GPJ)	Si-Di	Gl, 225V, 0,4A, 15pF(4V)	31a	Gie, Tix, ++	BA157..159, BY206..207, BY404..405, +
1N645(A,B,GPJ)	Si-Di	J: 250V	-	-	-
1N645J	Si-Di	-	31a	Gl, Tix, ++	BA157..159, BY206..207, BY404..405, +
1N646(GP)	Si-Di	=1N645: 300V	31a	-	BA157..159, BY206..207, BY404..405, +
1N6461	Z-Di	TAZ, 5V, 2,5W, 500W(1ms)	31a	Uni	BZW06/.., BZW70/.., BZX70/.., BZY93/..
1N6462	Z-Di	=1N6461: 6V	31a	-	-
1N6463	Z-Di	=1N6461: 12V	31a	-	-
1N6464	Z-Di	=1N6461: 15V	31a	-	-
1N6465	Z-Di	=1N6461: 24V	31a	-	-
1N6466	Z-Di	=1N6461: 30,5V	31a	-	-
1N6467	Z-Di	=1N6461: 40,3V	31a	-	-
1N6468	Z-Di	=1N6461: 51,6V	31a	-	-
1N647(GP)	Si-Di	=1N645: 400V	31a	-	BA157..159, BY207, BY404..405, +
1N6478	Si-Di	SMD, Gl, 50V, 1A, 15pF(4V)	72a(Smm)	Gie	BYM11-50, BYM12-50
1N6479	Si-Di	=1M6478: 100V	72a(Smm)	-	BYM11-100, BYM12-100
1N648(GP)	Si-Di	=1N645: 500V	31a	-	BA158..159, BY207, BY405, 1N4005, +
1N6480	Si-Di	=1M6478: 200V	72a(Smm)	-	BYM11-200, BYM12-200
1N6481	Si-Di	=1M6478: 400V	72a(Smm)	-	BYM11-400, BYM12-400
1N6482	Si-Di	=1M6478: 600V	72a(Smm)	-	BYM11-600, BYM12-600
1N6483	Si-Di	=1M6478: 800V	72a(Smm)	-	BYM11-800, BYM12-800
1N6484	Si-Di	=1M6478: 1000V	72a(Smm)	-	BYM11-1000, BYM12-1000
1N649(GP)	Si-Di	=1N645: 600V	31a	-	BA158..159, BY207, BY405, 1N4005, +
1N6492	Si-Di	Schottky-Gl, 45V, 1,2A, Uf<0,48V(1A)	2c	Uni	(BYS22-45, BYS26-45, MBR350, ++)
1N6496	Si-Di	16x Di Array, 60V, <10ns	20Pin	Fch	-

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1N65	Ge-Di	HF-Dem,70V,50mA	31a	USA,Tho	AA113,1N34,1N54,1N60
1N650	GaAs-Di	Tunnel-Di	2	Tix	-
1N651	GaAs-Di	Tunnel-Di	2	Tix	-
1N652	GaAs-Di	Tunnel-Di	2	Tix	-
1N653	GaAs-Di	Tunnel-Di	2	Tix	-
1N658(A)	Si-Di	S,50V,60mA,<300ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N659(A)	Si-Di	S,50V,100mA,<300ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N66(A)	Ge-Di	Uni,60V,50mA,A:<1pF(10V)	31a	USA,Tho	AA117..118,AA132..134,1N60,+
1N660(A)	Si-Di	S,100V,100mA,<300ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N6609	LED	~=4.8mm I=50mcd Uf=2V If=20mA	T046	Hpa	-
1N661(A)	Si-Di	S,200V,100mA,<300ns	31a	Fch,Tix,++	BA195,BA197..98,BAW50,BAX17,+
1N6610	LED	~=4.8mm I=50mcd Uf=2V If=20mA	T046	Hpa	-
1N6611	LED	~=4.8mm I=50mcd Uf=2.1V If=20mA	T046	Hpa	-
1N662(A)	Si-Di	S,80V,40mA,<500ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N6620	Si-Di	S,contr.av.,200V,1,2A,<30ns	31a	Uni	BYD73D..G,BYV27/200
1N6621	Si-Di	S,contr.av.,400V,1,2A,<30ns	31a	Uni	BYD73G,BYD74G
1N6622	Si-Di	S,contr.av.,600V,1,2A,<30ns	31a	Uni	-
1N6623	Si-Di	S,contr.av.,800V,1A,<50ns	31a	Uni	-
1N6624	Si-Di	S,contr.av.,900V,1A,<50ns	31a	Uni	-
1N6625	Si-Di	S,contr.av.,1000V,1A,<60ns	31a	Uni	-
1N6626	Si-Di	S,contr.av.,200V,2A,<30ns	31a	Uni	BYD74D..G,BYV27/200
1N6627	Si-Di	S,contr.av.,400V,2A,<30ns	31a	Uni	BYD74G
1N6628	Si-Di	S,contr.av.,600V,2A,<30ns	31a	Uni	-
1N6629	Si-Di	S,contr.av.,800V,1,4A,<50ns	31a	Uni	-
1N663(A)	Si-Di	S,80V,60mA,<500ns	31a	Fch,Tix,++	BA195,BAW49,BAX15..17,1N3070,+
1N6630	Si-Di	S,contr.av.,900V,1,4A,<50ns	31a	Uni	-
1N6631	Si-Di	S,contr.av.,1000V,1,4A,<60ns	31a	Uni	-
1N6638	Si-Di	SS,150V,0,3A,<2pF(0V),<4,5ns	31a	Uni	-
1N6638U..6643U	Si-Di	=1N6638..6643:SMD	72a	-	-
1N664	Z-Di	8,2V,5%,0,4W	34a	USA	BZX55/..,BZX83/..,ZPD..,1N5230..76,+
1N6642	Si-Di	SS,100V,0,3A,<5pF(0V),<5ns	31a	Uni	-
1N6643	Si-Di	SS,75V,0,3A,<5pF(0V),<6ns	31a	Uni	BAV10,BAW55,BAW76
1N665	Z-Di	=1N664:12V	34a	-	-
1N666	Z-Di	=1N664:15V	34a	-	-
1N667	Z-Di	=1N664:18V	34a	-	-
1N668	Z-Di	=1N664:22V	34a	-	-
1N669	Z-Di	=1N664:27V	34a	-	-
1N67(A)	Ge-Di	Dem,Uni,92V,35mA,A:80V,30mA	31a	USA,Tho	AA113,AA119,1N34,1N54,1N60,+
1N670	Z-Di	=1N664:68V	34a	-	-
1N671	Z-Di	=1N664:100V	34a	-	-
1N672	Z-Di	=1N664:150V	34a	-	-
1N673	Si-Di	Gl,350V,0,4A	?34a	USA	BA157..159,BY206..207,BY404..405,+
1N674	Z-Di	=1N664:4,7V	34a	USA	→1N664..
1N675	Z-Di	=1N664:6,2V	34a	USA	→1N664..
1N676	Si-Di	Gl,Uni,100V,0,2A	31a	Fch,Itt,++	BA157..159,BA193..194,BA199/250,+
1N677	Si-Di	Gl,Uni,100V,0,4A	31a	Fch,Itt,++	BA157..159,BA193..194,BA199/250,+
1N678	Si-Di	Gl,Uni,200V,0,2A	31a	Fch,Itt,++	BA157..159,BA199/250,BAS11,+
1N679	Si-Di	Gl,Uni,200V,0,4A	31a	Fch,Itt,++	BA157..159,BA199/250,BAS11,+
1N68(A)	Ge-Di	Uni,100V,35mA,A:30mA	31a	USA,Tho	AA117..118,AA132..133
1N681	Si-Di	Gl,Uni,300V,0,075A	31a	Fch,Itt,++	BA199/350,BAS11,BAY21,BAY88..90+
1N682	Si-Di	Gl,Uni,300V,0,15A	31a	Fch,Itt,++	BA199/350,BAS11,BAY21,BAY88..90+
1N683	Si-Di	Gl,Uni,400V,0,075A	31a	Fch,Itt,++	BA157..159,BA199/450,BAY89..90,+
1N684	Si-Di	Gl,Uni,400V,0,15A	31a	Fch,Itt,++	BA157..159,BA199/450,BAY89..90,+
1N685	Si-Di	Gl,Uni,500V,0,075A	31a	Fch,Itt,++	BA158..159,BA199/550,BAY89..90,+
1N686	Si-Di	Gl,Uni,500V,0,15A	31a	Fch,Itt,++	BA158..159,BA199/550,BAY89..90,+
1N687	Si-Di	Gl,Uni,600V,0,075A	31a	Fch,Itt,++	BA158..159,BA199/550,BAY89..90,+
1N689	Si-Di	Gl,Uni,600V,0,15A	31a	Fch,Itt,++	BA158..159,BA199/550,BAY89..90,+
1N69(A)	Ge-Di	Uni,70V,40mA,A:75V	31a	USA,Tho	AA117..118,AA132..134,1N34,1N54,+
1N690	Si-Di	Uni,S,36V,0,25A,<12pF,<800ns	31a	Ssi,Tix,++	BAV17..21,BAW48..50,BAY72,BAX12+
1N691	Si-Di	=1N690:80V	31a	-	BAV19..21,BAW49..50,BAY72,BAX12+
1N692	Si-Di	=1N690:100V	31a	-	BAV19..21,BAW49..50,BAY72,BAX12+
1N693	Si-Di	=1N690:130V	31a	-	BAV16,BAV19..21,BAW50,BAX15,+
1N695(A)	Ge-Di	S,20(A:25)V,0,1(A:0,15)A,300ns	31a	USA	AAY49,AAZ15,AAZ17
1N696	Si-Di	S,40V,<4pF(0V),<5ns	-	USA	BA318,BAY38,1N3062..64,1N4305,+

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1N697	Si-Di	S,120V,0,25A,<25pF(0V),<100ns	?34a	USA	BA197..98,BAV19..21,BAW50,+
1N698	Ge-Di	S,15V,500ns	31a	USA	AAY49,AAZ15,AAZ18,1N276
1N699	Ge-Di	S,105V,30mA,<300ns	31a	USA	AAY28,1N191,1N633
1N70(A)	Ge-Di	Uni,120V,30mA,A:125V,50mA	31a	USA,Tho	AA117..118,AA132..133
1N701	Z-Di	10V,5%,0,4W	?34a	USA	BZX55/C10,BZX83/C10,ZPD10,1N5240,+
1N702	Z-Di	2,6V,10%,0,25W	31a	USA,Tho	BZX55/..,BZX79/..,ZPD..,1N5222..81,+
1N702A...745A	Z-Di	=1N702..745:5%	31a	-	-
1N702A..745A	Z-Di	=1N702..745:5%	31a	-	-
1N702B...745B	Z-Di	=1N702..745:20%	31a	-	-
1N702B..745B	Z-Di	=1N702..745:20%	31a	-	-
1N703	Z-Di	=1N702:3,5V	31a	-	-
1N704	Z-Di	=1N702:4,1V	31a	-	-
1N705	Z-Di	=1N702:4,8V	31a	-	-
1N706	Z-Di	=1N702:5,8V	31a	-	-
1N707	Z-Di	=1N702:7,1V	31a	-	-
1N708	Z-Di	=1N702:5,6V	31a	-	-
1N709	Z-Di	=1N702:6,2V	31a	-	-
1N71	Ge-Di	=4x1N56gep	-	Alp	-
1N710	Z-Di	=1N702:6,8V	31a	-	-
1N711	Z-Di	=1N702:7,5V	31a	-	-
1N712	Z-Di	=1N702:8,2V	31a	-	-
1N713	Z-Di	=1N702:9,1V	31a	-	-
1N714	Z-Di	=1N702:10V	31a	-	-
1N715	Z-Di	=1N702:11V	31a	-	-
1N716	Z-Di	=1N702:12V	31a	-	-
1N717	Z-Di	=1N702:13V	31a	-	-
1N718	Z-Di	=1N702:15V	31a	-	-
1N719	Z-Di	=1N702:16V	31a	-	-
1N72	Ge-Di	UHF-M,900MHz	31a	Gen	-
1N720	Z-Di	=1N702:18V	31a	-	-
1N721	Z-Di	=1N702:20V	31a	-	-
1N722	Z-Di	=1N702:22V	31a	-	-
1N723	Z-Di	=1N702:24V	31a	-	-
1N724	Z-Di	=1N702:27V	31a	-	-
1N725	Z-Di	=1N702:30V	31a	-	-
1N726	Z-Di	=1N702:33V	31a	-	-
1N727	Z-Di	=1N702:36V	31a	-	-
1N728	Z-Di	=1N702:39V	31a	-	-
1N729	Z-Di	=1N702:43V	31a	-	-
1N73	Ge-Di	4xHF-Dem,gep,75V,22mA	4x31a	USA	AA113,1N34
1N730	Z-Di	=1N702:47V	31a	-	-
1N731	Z-Di	=1N702:51V	31a	-	-
1N732	Z-Di	=1N702:56V	31a	-	-
1N733	Z-Di	=1N702:62V	31a	-	-
1N734	Z-Di	=1N702:68V	31a	-	-
1N735	Z-Di	=1N702:75V	31a	-	-
1N736	Z-Di	=1N702:82V	31a	-	-
1N737	Z-Di	=1N702:91V	31a	-	-
1N738	Z-Di	=1N702:100V	31a	-	-
1N739	Z-Di	=1N702:110V	31a	-	-
1N74	Ge-Di	4xHF-Dem,gep,75V,22mA	-	USA	-
1N740	Z-Di	=1N702:120V	31a	-	-
1N741	Z-Di	=1N702:130V	31a	-	-
1N742	Z-Di	=1N702:150V	31a	-	-
1N743	Z-Di	=1N702:160V	31a	-	-
1N744	Z-Di	=1N702:180V	31a	-	-
1N745	Z-Di	=1N702:200V	31a	-	-
1N746	Z-Di	3,3V,10%,0,4W	31a	USA,Tho	BZX55/..,BZX83/..,ZPD..,1N5226..42,+
1N746A	Z-Di	3.3V,0.5W,Zzt=28Ω	-	Fairchild	-
1N746A...759A	Z-Di	=1N746..759:5%	31a	-	-
1N746A..759A	Z-Di	=1N746..759:5%	31a	-	-
1N747	Z-Di	=1N746:3,6V	31a	-	-
1N747A	Z-Di	3.6V,0.5W,Zzt=24Ω	-	Fairchild	-
1N748	Z-Di	=1N746:3,9V	31a	-	-

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1N748A	Z-Di	3.9V,0.5W,Zzt=23Ω	31a	Fairchild	-
1N749	Z-Di	=1N746:4,3V	31a	-	-
1N749A	Z-Di	4.3V,0.5W,Zzt=22Ω	31a	Fairchild	-
1N75	Ge-Di	HF,Uni,100V,50mA	31a	USA,Tho	AA117..118,AA132..133
1N750	Z-Di	=1N746:4,7V	31a	-	-
1N750A	Z-Di	4.7V,0.5W,Zzt=19Ω	31a	Fairchild	-
1N751	Z-Di	=1N746:5,1V	31a	-	-
1N751A	Z-Di	5.1V,0.5W,Zzt=17Ω	31a	Fairchild	-
1N752	Z-Di	=1N746:5,6V	31a	-	-
1N752A	Z-Di	5.6V,0.5W,Zzt=11Ω	31a	Fairchild	-
1N753	Z-Di	=1N746:6,2V	31a	-	-
1N753A	Z-Di	6.2V,0.5W,Zzt=7Ω	31a	Fairchild	-
1N754	Z-Di	=1N746:6,8V	31a	-	-
1N754A	Z-Di	6.8V,0.5W,Zzt=5Ω	31a	Fairchild	-
1N754AT	Z-Di	6.8V,0.5W,Zzt=5Ω	-	Fairchild	-
1N755	Z-Di	=1N746:7,5V	31a	-	-
1N755A	Z-Di	7.5V,0.5W,Zzt=6Ω	-	Fairchild	-
1N755AT	Z-Di	7.5V,0.5W,Zzt=6Ω	-	Fairchild	-
1N756	Z-Di	=1N746:8,2V	31a	-	-
1N756A	Z-Di	8.2V,0.5W,Zzt=8Ω	-	Fairchild	-
1N756AT	Z-Di	8.2V,0.5W,Zzt=8Ω	-	Fairchild	-
1N757	Z-Di	=1N746:9,1V	31a	-	-
1N757A	Z-Di	9.1V,0.5W,Zzt=10Ω	-	Fairchild	-
1N757AT	Z-Di	9.1V,0.5W,Zzt=10Ω	-	Fairchild	-
1N758	Z-Di	=1N746:10V	31a	-	-
1N758A	Z-Di	10V,0.5W,Zzt=17Ω	-	Fairchild	-
1N758AT	Z-Di	10V,0.5W,Zzt=17Ω	-	Fairchild	-
1N759	Z-Di	=1N746:12V	31a	-	-
1N759A	Z-Di	12V,0.5W,Zzt=30Ω	-	Fairchild	-
1N759AT	Z-Di	12V,0.5W,Zzt=30Ω	-	Fairchild	-
1N76	Si-Di	UHF,X-Band-Dem,9375MHz	Koax	USA	-
1N760	Ge-Di	S,60V,100ns	31a	USA	1N631,1N633
1N761	Z-Di	4,85V,10%,0,25W	31a	Mot,Tix,++	BZX55/..,BZX79/..,ZPD..,1N5230..52,+
1N761A...769A	Z-Di	=1N761..769:5%	31a	-	-
1N761A..769A	Z-Di	=1N761..769:5%	31a	-	-
1N762	Z-Di	=1N761:5,8V	31a	-	-
1N763	Z-Di	=1N761:7,1V	31a	-	-
1N764	Z-Di	=1N761:8,75V	31a	-	-
1N765	Z-Di	=1N761:10,5V	31a	-	-
1N766	Z-Di	=1N761:12,7V	31a	-	-
1N767	Z-Di	=1N761:15,7V	31a	-	-
1N768	Z-Di	=1N761:19V	31a	-	-
1N769	Z-Di	=1N761:23,5V	31a	-	-
1N77	Opto	-		-	-
1N770	Ge-Di	S,20V,40mA,350ns	31a	USA	AAY29,1N191..192
1N771(A,B)	Ge-Di	Uni,100V,50mA,A:65mA,B:75mA	31a	USA,Gle	AA117..118,AA132..133
1N772(A)	Ge-Di	Uni,80V,50mA,A:65mA	31a	USA,Gle	AA117..118,AA132..133
1N773(A)	Ge-Di	Uni,75V,50mA,A:65mA	31a	USA,Gle	AA117..118,AA132..134,1N34,1N54,+
1N774(A)	Ge-Di	Uni,70V,50mA,A:65mA	31a	USA,Gle	AA117..118,AA132..134,1N34,1N54,+
1N775	Ge-Di	Uni,70V,50mA	31a	USA,Gle	AA117..118,AA132..134,1N34,1N54,+
1N776	Ge-Di	Uni,30V,45mA	31a	USA,Gle	AA117..118,AA132..134,1N34,1N54,+
1N777	Ge-Di	S,75V,50mA,500ns	31a	USA	AAY28,1N276,1N633
1N778	Si-Di	S,118V,50mA,300ns	31a	USA	BA195,BAV19..21,BAX15..17,+
1N779	Si-Di	S,200V,50mA,300ns	31a	USA	BA195,BA197..198,BAV20..21,BAX17
1N78	Si-Di	UHF,Ku-Band-M,16GHz	Koax	USA	-
1N781(A)	Ge-Di	S,40V,60mA,<500ns	31a	USA	AAY28,1N191..192,1N276
1N788	Ge-Di	S,60V,200ns	31a	USA	-
1N789	Si-Di	S,30V,0,12A,<500ns	31a	USA	BA195,BAV17..21,BAX15..17,1N3070+
1N79	Di	Mess-Gl,Meter rectifier,<3GHz	Koax	Alp	-
1N790	Si-Di	S,30V,0,12A,<250ns	31a	USA	BA195,BAV17..21,BAX15..17,1N3070+
1N791	Si-Di	S,30V,0,16A,<500ns	31a	USA	BA195,BAV17..21,BAX15..17,1N3070+
1N792	Si-Di	S,30V,0,2A,<500ns	31a	USA	BA195,BAV17..21,BAX15..17,1N3070+
1N793	Si-Di	S,60V,0,12A,<500ns	31a	USA	BA195,BAV18..21,BAX15..17,1N3070+
1N794	Si-Di	S,60V,0,12A,<250ns	31a	USA	BA195,BAV18..21,BAX15..17,1N3070+

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1N795	Si-Di	S,60V,0,16A,<500ns	31a	USA	BA195,BAV18..21,BAX15..17,1N3070+
1N796	Si-Di	S,60V,0,2A,<500ns	31a	USA	BA195,BAV18..21,BAX15..17,1N3070+
1N797	Si-Di	S,120V,0,12A,<500ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N798	Si-Di	S,120V,0,12A,<250ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N799	Si-Di	S,120V,0,16A,<500ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N800	Si-Di	S,120V,0,2A,<500ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N801	Si-Di	S,150V,0,12A,<500ns	31a	USA	BA195,BAV20..21,BAX15..17,1N3070+
1N802	Si-Di	S,150V,0,16A,<500ns	31a	USA	BA195,BAV20..21,BAX15..17,1N3070+
1N803	Si-Di	S,200V,0,12A,<500ns	31a	USA	BA195,BA197..198,BAV20..21,+
1N804	Si-Di	S,200V,0,16A,<500ns	31a	USA	BA195,BA197..198,BAV20..21,+
1N805	Ge-Di	Uni,40V	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N806	Si-Di	S,125V,60mA,<300ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N807	Si-Di	S,200V,60mA,<300ns	31a	USA	BA195,BA197..198,BAV20..21,BAX17
1N808	Si-Di	S,110V,100mA,<300ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N809	Si-Di	S,220V,100mA,<300ns	31a	USA	BA195,BA197..198,BAV20..21,BAX17
1N81(A)	Ge-Di	Uni,50V,30mA	31a	USA,Nec,Tho	AA117..118,AA132..134,1N60,+
1N810	Si-Di	S,50V,<7pF(0V),<50ns	?34a	USA	BY208/600,BY295/150,BY406..407,+
1N811	Si-Di	S,30V,0,04A,<2pF(0V),<250ns	31a	USA	BAV17..21,BAX15..17,1N3070,+
1N812	Si-Di	S,40V,0,06A,<2pF(0V),<250ns	31a	USA	BAV18..21,BAX15..17,1N3070,+
1N813	Si-Di	S,20V,0,075A,<2pF(0V),<250ns	31a	USA	BAV17..21,BAX15..17,1N3070,+
1N814	Si-Di	S,50V,0,06A,<1pF(0V),<250ns	31a	USA	BAV18..21,BAX15..17,1N3070,+
1N815	Si-Di	S,25V,0,12A,<3pF(0V),<250ns	31a	USA	BAV17..21,BAX15..17,1N3070,+
1N816	Si-St	0,58..0,7V	31a	USA,Mot	BA220,BZ102/0V7,BZX55/C0V8,BZX62,+
1N817	Si-Di	S,200V,<1?s	31a	old	BA147/230,BA190,1N5195..96,+
1N818	Si-Di	S,80V,0,055A,<500ns	31a	USA	BA195,BAV19..20,BAX15..17,1N3070+
1N819	Si-Di	80V	-		-
1N82(A)	Si-Di	UHF-M,5V,890MHz	31a	Tho	-
1N821(A)	Ref-Di	6,2V,5%,0,25W	31a	USA,EUR	BZV10,BZV27,BZX90
1N822(A)	Ref-Di	bidirektional,6,2V,5%,0,25W	31a	-	-
1N823(A)	Ref-Di	6,2V,5%,0,25W	31a	-	BZV11,BZV28,BZX91
1N824(A)	Ref-Di	bidirektional,6,2V,5%,0,25W	31a	-	-
1N825(A)	Ref-Di	6,2V,5%,0,25W	31a	-	BZV12,BZV29,BZX92
1N826(A)	Ref-Di	6,55V,5%,0,25W	31a	-	BZV12,BZV29,BZX92
1N827(A)	Ref-Di	6,2V,5%,0,25W	31a	-	BZV13,BZV30,BZX93
1N828(A)	Ref-Di	6,55V,5%,0,25W	31a	-	BZV13,BZV30,BZX93
1N829(A)	Ref-Di	6,2V,5%,0,25W	31a	-	BZV14,BZV51,BZX94
1N83	Ge-Di	Uni,375V	31a	Idc	-
1N830(A)	Si-Di	UHF-Dem,2V,25mA	31a	USA	-
1N831(A,B,C)	Si-Di	UHF,S-Band-M,3060MHz	31a	USA	-
1N832(A,B,C)	Si-Di	UHF,X-Band-M,9375MHz	31a	USA	-
1N833(A)	Si-Di	UHF,X-Band-Dem,9375MHz	31a	USA	-
1N835	Ge-Di	S,30V,70mA,<500ns	31a	USA	AAY49,AAZ15,AAZ17
1N836	Ge-Di	UHF,5V	31a	old	-
1N837(A)	Si-Di	S,100V,0,1A,<500ns,A:<300ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N838	Si-Di	S,150V,0,1A,5pF(0V),<500ns	31a	USA	BA195,BAV20..21,BAX15..17,1N3070+
1N839	Si-Di	S,200V,0,1A,5pF(0V),<500ns	31a	USA	BA195,BA197..198,BAV20..21,BAX17
1N84	Ge-Di	HF,Uni,25V	31a	USA	AA113,AA119,1N34,1N54,1N60
1N840	Si-Di	S,50V,0,1A,5pF(0V),<300ns	31a	USA	BA195,BAV18..21,BAX15..17,1N3070+
1N841	Si-Di	S,150V,0,1A,5pF(0V),<300ns	31a	USA	BA195,BAV20..21,BAX15..17,1N3070+
1N842	Si-Di	S,200V,0,1A,5pF(0V),<300ns	31a	USA	BA195,BA197..198,BAV20..21,BAX17
1N843	Si-Di	S,250V,0,1A,5pF(0V),<300ns	31a	USA	BA198,BAV21,BAW173
1N844	Si-Di	S,100V,0,2A,5pF(0V),<500ns	31a	USA	BA195,BAV19..21,BAX15..17,1N3070+
1N845	Si-Di	S,200V,0,2A,5pF(0V),<500ns	31a	USA	BA195,BA197..198,BAV19..21,BAX17
1N846	Si-Di	Gl,Uni,50V,0,2A	31a	USA	BA157..159,BAY86..90,BY204/4,+
1N847	Si-Di	=1N846:100V	31a	-	BA157..159,BAY87..90,BY204/4,+
1N848	Si-Di	=1N846:200V	31a	-	BA157..159,BAY88..90,BY204/4,+
1N849	Si-Di	=1N846:300V	31a	-	BA157..159,BAY88..90,BY204/4,+
1N85	Opto	-		-	-
1N850	Si-Di	=1N846:400V	31a	-	BA157..159,BAY89..90,BY204/4,+
1N851	Si-Di	=1N846:500V	31a	-	BA158..159,BAY89..90,BY204/8,+
1N852	Si-Di	=1N846:600V	31a	-	BA158..159,BAY89..90,BY204/8,+
1N853	Si-Di	=1N846:700V	31a	-	BA158..159,BAY90..91,BY204/8,+
1N854	Si-Di	=1N846:800V	31a	-	BA158..159,BAY90..91,BY204/8,+
1N855	Si-Di	=1N846:900V	31a	-	BA159,BAY90..91,BY204/10,+

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1N856	Si-Di	=1N846: 1000V	31a	-	BA159, BAY90..91, BY204/10, +
1N857	Si-Di	Gl, Uni, 50V, 0,15A	31a	USA	BA157..159, BAY86..90, BY204/4, +
1N858	Si-Di	=1N857: 100V	31a	-	BA157..159, BAY87..90, BY204/4, +
1N859	Si-Di	=1N857: 200V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N86	Ge-Di	Uni, 70V, 50mA	31a	USA	AA117..118, AA132..134
1N860	Si-Di	=1N857: 300V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N861	Si-Di	=1N857: 400V	31a	-	BA157..159, BAY89..90, BY204/4, +
1N862	Si-Di	=1N857: 500V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N863	Si-Di	=1N857: 600V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N864	Si-Di	=1N857: 700V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N865	Si-Di	=1N857: 800V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N866	Si-Di	=1N857: 900V	31a	-	BA159, BAY90..91, BY204/10, +
1N867	Si-Di	=1N857: 1000V	31a	-	BA159, BAY90..91, BY204/10, +
1N868	Si-Di	Gl, Uni, 50V, 0,1A	31a	USA	BA157..159, BAY86..90, BY204/4, +
1N869	Si-Di	=1N868: 100V	31a	-	BA157..159, BAY87..90, BY204/4, +
1N87(A..T)	Ge-Di	AM/FM-Dem, 25..30V, 30..50mA	31a	USA, EUR, Tos	AA112..114, AA119, 1N34, 1N54, 1N60, +
1N870	Si-Di	=1N868: 200V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N871	Si-Di	=1N868: 300V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N872	Si-Di	=1N868: 400V	31a	-	BA157..159, BAY89..90, BY204/4, +
1N873	Si-Di	=1N868: 500V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N874	Si-Di	=1N868: 600V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N875	Si-Di	=1N868: 700V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N876	Si-Di	=1N868: 800V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N877	Si-Di	=1N868: 900V	31a	-	BA159, BAY90..91, BY204/10, +
1N878	Si-Di	=1N868: 1000V	31a	-	BA159, BAY90..91, BY204/10, +
1N879	Si-Di	Gl, Uni, 50V, 0,05A	31a	USA	BA157..159, BAY86..90, BY204/4, +
1N88	Ge-Di	HF, Uni, 100V	31a	USA	AA117..118, AA132..133
1N880	Si-Di	=1N879: 100V	31a	-	BA157..159, BAY87..90, BY204/4, +
1N881	Si-Di	=1N879: 200V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N882	Si-Di	=1N879: 300V	31a	-	BA157..159, BAY88..90, BY204/4, +
1N883	Si-Di	=1N879: 400V	31a	-	BA157..159, BAY89..90, BY204/4, +
1N884	Si-Di	=1N879: 500V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N885	Si-Di	=1N879: 600V	31a	-	BA158..159, BAY89..90, BY204/8, +
1N886	Si-Di	=1N879: 700V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N887	Si-Di	=1N879: 800V	31a	-	BA158..159, BAY90..91, BY204/8, +
1N888	Si-Di	=1N879: 900V	31a	-	BA159, BAY90..91, BY204/10, +
1N889	Si-Di	=1N879: 1000V	31a	-	BA159, BAY90..91, BY204/10, +
1N89	Ge-Di	Uni, 80V, 30mA, 1pF(0V)	31a	USA	AA117..118, AA132..133
1N890	Si-Di	Uni, 80V, 0,1A, 10pF(0V)	31a	USA	BA147/100, BA188..190, 1N5606..09, +
1N891	Si-Di	S, 60V, 0,2A, 300ns	31a	USA	BA197..198, BAV18..21, BAX15..17, +
1N892	Si-Di	S, 120V, 0,2A, 300ns	31a	USA	BA197..198, BAV20..21, BAX15..17, +
1N893	Si-Di	S, 240V, 0,2A, 300ns	31a	USA	BA173, BA198, BAV21
1N894	Ge-Di	UHF, 5V	-	old	-
1N895	Ge-Di	UHF, 5V	-	old	-
1N896	Ge-Di	UHF, 5V	-	old	-
1N897	Si-Di	Min, S, Uni, 50V, 0,03A, <1?s	31a	Sem	(BAX85, BAX89, BAX90, BAX94, ++)
1N898	Si-Di	Min, S, Uni, 50V, 0,06A, <300ns	31a	Sem	(BAX85, BAX89, BAX90, BAX94, ++)
1N899	Si-Di	Min, S, Uni, 100V, 0,03A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N90	Ge-Di	Uni, 60V, 30mA, 1pF(0V)	31a	USA, Tho	AA117..118, AA132..134, 1N34, 1N54, +
1N900	Si-Di	Min, S, Uni, 100V, 0,05A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N901	Si-Di	Min, S, Uni, 100V, 0,06A, <300ns	31a	Sem	(BA197..198, BAV19..21, BAX15..17, ++)
1N902	Si-Di	Min, S, Uni, 200V, 0,03A, <300ns	31a	Sem	(BA197..198, BAV20..21, BAX17, ++)
1N903(A)	Si-Di	S, 20V, 50mA, <4ns, A: 40V, 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N904(A)	Si-Di	S, 30V, 50mA, <4as, A: 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N905(A)	Si-Di	S, 20V, 50mA, <4ns, A: 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N906(A)	Si-Di	S, 20V, 50mA, <4ns, A: 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N907(A)	Si-Di	S, 30V, 50mA, <4as, A: 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N908(A)	Si-Di	S, 40V, 50mA, <4ns, A: 75mA	31a	USA, Sgs	BA218, BAX13, BAX91, 1N4148, +
1N909	Ge-Di	Uni, 60V, 100mA	31a	USA	AA136, 1N270, 1N634..635
1N91	Ge-Di	Gl, 100V, 1A	34a	Gen, Mot, Sld	-
1N910	Ge-Di	=1N909: 30V	31a	-	AA135..136, 1N270, 1N634..635
1N911	Ge-Di	=1N909: 30V	31a	-	AA135..136, 1N270, 1N634..635
1N912(A)	Ref-Di	0,62V, 0,5W	31a	USA	-
1N913(A)	Ref-Di	0,62V, 0,6W	31a	USA	-

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1N914(A,B)	Si-Di	SS,100V,0,2A,<4pF,<4ns	31a	USA,EUR,JAP	BAW62,BAX95,1N4148..49,1N4151,+
1N915	Si-Di	S,65V,0,075A,<4pF,<10ns	31a	Hit,Tix	BAW62,BAX95,1N4148..49,1N4151,+
1N916(A,B)	Si-Di	SS,100V,0,2A,<2pF,<4ns	31a	USA,EUR,JAP	BAW62,BAX95,1N4148..49,1N4151,+
1N917	Si-Di	SS,40V,0,05A,<2,5pF,<3ns	31a	Hit,Tix	BAW62,BAX95,1N4148..49,1N4151,+
1N918	Si-Di	UHF,Ku-Band-M,16GHz	31a	Syl	-
1N919	Si-Di	S,150V,0,1A,<300ns	31a	USA	BA195,BAV20..21,BAX15..17,1N3070+
1N92	Ge-Di	=1N91:200V	34a	-	-
1N920	Si-Di	S,36V,0,25A,<7,5pF,<300ns	31a	USA	BA197..189,BAV17..21,BAX15..17,+
1N921	Si-Di	S,70V,0,25A,<7,5pF,<300ns	31a	USA	BA197..189,BAV19..21,BAX15..17,+
1N922	Si-Di	S,100V,0,25A,<7,5pF,<300ns	31a	USA	BA197..189,BAV19..21,BAX15..17,+
1N923	Si-Di	S,130V,0,25A,<7,5pF,<300ns	31a	USA	BA197..189,BAV19..21,BAX15..17,+
1N924	Si-Di	Uni,S,60V,2?s	31a	USA	BA127,BA188..190,BAY19..21,+
1N925	Si-Di	S,40V,0,12A,<4pF,<150ns	31a	USA	BA195,BAX16..17,BAY41..43,1N3070+
1N926	Si-Di	S,40V,0,12A,<4pF,<150ns	31a	USA	BA195,BAX16..17,BAY41..43,1N3070+
1N927	Si-Di	S,65V,0,12A,<4pF,<150ns	31a	USA	BA195,BAX16..17,BAY42..43,1N3070+
1N928	Si-Di	=1N927:120V	31a	-	BA195,BAX16..17,BAV19..21,1N3070+
1N929	Si-Di	Uni,23V,0,25A	31a	USA	BA192..194,BAW51..52,BAY17..21,+
1N93(A)	Ge-Di	=1N91:300V	34a	-	-
1N930	Si-Di	Uni,58V,0,25A	31a	USA	BA193..194,BAW51..52,BAY19..21,+
1N931	Si-Di	Uni,115V,0,25A	31a	USA	BA194,BAW52,BAY20..21,BAY45,+
1N932	Si-Di	Uni,230V,0,25A	31a	USA	BA199/250,BAY21,BAY46,BAY88,+
1N933	Ge-Di	S,100V,30mA,<1pF,<400ns	31a	USA	AAY28,AAZ15,1N633
1N934	Si-Di	S,60V,30mA,1?s	31a	USA	BA127,BA147/100,BA188..190,+
1N935(A,B)	Ref-Di	9V,5%,0,5W	31a	USA,EUR	1N4765
1N936(A,B)	Ref-Di	9V,5%,0,5W	31a	-	1N4766,1N4771
1N937(A,B)	Ref-Di	9V,5%,0,5W	31a	-	1N4767,1N4772
1N938(A,B)	Ref-Di	9V,5%,0,5W	31a	-	1N4768,1N4773
1N939(A,B)	Ref-Di	9V,5%,0,5W	31a	-	1N4769,1N4774
1N94	Ge-Di	Gl,380V,0,5A	-		-
1N940(A,B)	Ref-Di	9V,5%,0,5W	31a	-	-
1N941(A,B)	Ref-Di	11,7V,5%,0,5W	31a	USA,JAP	1N3580
1N942(A,B)	Ref-Di	11,7V,5%,0,5W	31a	-	1N3581
1N943(A,B)	Ref-Di	11,7V,5%,0,5W	31a	-	1N3582
1N944(A,B)	Ref-Di	11,7V,5%,0,5W	31a	-	1N3583
1N945(A,B)	Ref-Di	11,7V,5%,0,5W	31a	-	1N3584
1N946(A,B)	Ref-Di	11,7V,5%,0,5W	31a	-	-
1N947	Si-Di	Gl,600V,0,4A	?34a	USA	BA158..159,BY204/8,BY207,BY405,+
1N948	Si-Di	S,36V,0,08A,<1?s	31a	USA	BA127,BA147/50,BA187..190,+
1N949	Ge-Di	Uni,50V,Ifsm=0,5A	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N95	Ge-Di	Uni,60V,30mA	31a	USA	AA117..118,AA132..134,1N34,1N54,+
1N950(A)	Si-Di	VHF-Tuning,130V,6..88pF(0/130V)	31a	USA	-
1N951(A)	Si-Di	VHF-Tuning,80V,12..120pF(0/80V)	31a	USA	-
1N952(A)	Si-Di	VHF-Tuning,60V,20..170pF(0/60V)	31a	USA	-
1N953(A)	Si-Di	VHF-Tuning,25V,46..240pF(0/25V)	31a	USA	-
1N954	Si-Di	VHF-Tuning,25V,14..88pF(0/25V)	31a	USA	-
1N955	Si-Di	VHF-Tuning,25V,22..120pF(0/25V)	31a	USA	-
1N956	Si-Di	VHF-Tuning,25V,32..170pF(0/25V)	31a	USA	-
1N957	Z-Di	6,8V,20%,0,4W	31a	USA,EUR,JAP	BZX55/..,BZX83/..,ZPD..,1N5235..81,+
1N957A...992A	Z-Di	=1N957..992:10%	31a	-	-
1N957A..992A	Z-Di	=1N957..992:10%	31a	-	-
1N957B	Z-Di	6.8V,0.5W,Zzt=4.5Ω	-	Fairchild	-
1N957B...992B	Z-Di	=1N957..992:5%	31a	-	-
1N957B..992B	Z-Di	=1N957..992:5%	31a	-	-
1N957BT	Z-Di	6.8V,0.5W,Zzt=4.5Ω	-	Fairchild	-
1N958	Z-Di	=1N957:7,5V	31a	-	-
1N958B	Z-Di	7.5V,0.5W,Zzt=5.5Ω	-	Fairchild	-
1N958BT	Z-Di	7.5V,0.5W,Zzt=5.5Ω	-	Fairchild	-
1N959	Z-Di	=1N957:8,2V	31a	-	-
1N959B	Z-Di	8.2V,0.5W,Zzt=6.5Ω	-	Fairchild	-
1N959BT	Z-Di	8.2V,0.5W,Zzt=6.5Ω	-	Fairchild	-
1N96(A)	Ge-Di	Uni,75V,30mA,A:70mA	31a	USA,Nec,Tho	AA117..118,AA132..134,1N34,1N54,+
1N960	Z-Di	=1N957:9,1V	31a	-	-
1N960B	Z-Di	9.1V,0.5W,Zzt=7.5Ω	-	Fairchild	-
1N960BT	Z-Di	9.1V,0.5W,Zzt=7.5Ω	-	Fairchild	-

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1N961	Z-Di	=1N957:10V	31a	-	-
1N961B	Z-Di	10V,0.5W,Zzt=8.5Ω	-	Fairchild	-
1N961BT	Z-Di	10V,0.5W,Zzt=8.5Ω	-	Fairchild	-
1N962	Z-Di	=1N957:11V	31a	-	-
1N962B	Z-Di	11V,0.5W,Zzt=9.5Ω	-	Fairchild	-
1N962BT	Z-Di	11V,0.5W,Zzt=9.5Ω	-	Fairchild	-
1N963	Z-Di	=1N957:12V	31a	-	-
1N963B	Z-Di	12V,0.5W,Zzt=11.5Ω	-	Fairchild	-
1N963BT	Z-Di	12V,0.5W,Zzt=11.5Ω	-	Fairchild	-
1N964	Z-Di	=1N957:13V	31a	-	-
1N964B	Z-Di	13V,0.5W,Zzt=13Ω	-	Fairchild	-
1N964BT	Z-Di	13V,0.5W,Zzt=13Ω	-	Fairchild	-
1N965	Z-Di	=1N957:15V	31a	-	-
1N965B	Z-Di	15V,0.5W,Zzt=16Ω	-	Fairchild	-
1N965BT	Z-Di	15V,0.5W,Zzt=16Ω	-	Fairchild	-
1N966	Z-Di	=1N957:16V	31a	-	-
1N966B	Z-Di	16V,0.5W,Zzt=17Ω	-	Fairchild	-
1N966BT	Z-Di	16V,0.5W,Zzt=17Ω	-	Fairchild	-
1N967	Z-Di	=1N957:18V	31a	-	-
1N967B	Z-Di	18V,0.5W,Zzt=21Ω	-	Fairchild	-
1N967BT	Z-Di	18V,0.5W,Zzt=21Ω	-	Fairchild	-
1N968	Z-Di	=1N957:20V	31a	-	-
1N968B	Z-Di	20V,0.5W,Zzt=25Ω	-	Fairchild	-
1N968BT	Z-Di	20V,0.5W,Zzt=25Ω	-	Fairchild	-
1N969	Z-Di	=1N957:22V	31a	-	-
1N969B	Z-Di	22V,0.5W	-	Fairchild	-
1N97(A)	Ge-Di	Uni,80V,30mA,A:92V	31a	USA	AA117..118,AA132..133
1N970	Z-Di	=1N957:24V	31a	-	-
1N970B	Z-Di	24V,0.5W,Zzt=33Ω	-	Fairchild	-
1N971	Z-Di	=1N957:27V	31a	-	-
1N971B	Z-Di	27V,0.5W,Zzt=41Ω	-	Fairchild	-
1N972	Z-Di	=1N957:30V	31a	-	-
1N972B	Z-Di	30V,0.5W,Zzt=49Ω	-	Fairchild	-
1N973	Z-Di	=1N957:33V	31a	-	-
1N973B	Z-Di	33V,0.5W,Zzt=58Ω	-	Fairchild	-
1N974	Z-Di	=1N957:36V	31a	-	-
1N974B	Z-Di	36V,0.5W,Zzt=70Ω	-	Fairchild	-
1N975	Z-Di	=1N957:39V	31a	-	-
1N975B	Z-Di	39V,0.5W,Zzt=80Ω	-	Fairchild	-
1N976	Z-Di	=1N957:43V	31a	-	-
1N976B	Z-Di	43V,0.5W,Zzt=93Ω	-	Fairchild	-
1N977	Z-Di	=1N957:47V	31a	-	-
1N977B	Z-Di	47V,0.5W,Zzt=105Ω	-	Fairchild	-
1N978	Z-Di	=1N957:51V	31a	-	-
1N978B	Z-Di	51V,0.5W,Zzt=125Ω	-	Fairchild	-
1N979	Z-Di	=1N957:56V	31a	-	-
1N979B	Z-Di	62V,0.5W,Zzt=185Ω	-	Fairchild	-
1N98(A)	Ge-Di	HF-Dem,80V,30mA,A:70mA	31a	USA,Tho	1N34,1N54
1N980	Z-Di	=1N957:62V	31a	-	-
1N980B	Z-Di	62V,0.5W,Zzt=185Ω	-	Fairchild	-
1N981	Z-Di	=1N957:68V	31a	-	-
1N981B	Z-Di	68V,0.5W,Zzt=230Ω	-	Fairchild	-
1N982	Z-Di	=1N957:75V	31a	-	-
1N982B	Z-Di	75V,0.5W,Zzt=270Ω	-	Fairchild	-
1N983	Z-Di	=1N957:82V	31a	-	-
1N983B	Z-Di	82V,0.5W,Zzt=330Ω	-	Fairchild	-
1N984	Z-Di	=1N957:91V	31a	-	-
1N984B	Z-Di	91V,0.5W,Zzt=400Ω	-	Fairchild	-
1N985	Z-Di	=1N957:100V	31a	-	-
1N985B	Z-Di	100V,0.5W,Zzt=500Ω	-	Fairchild	-
1N986	Z-Di	=1N957:110V	31a	-	-
1N986B	Z-Di	110V,0.5W,Zzt=750Ω	-	Fairchild	-
1N987	Z-Di	=1N957:120V	31a	-	-
1N988	Z-Di	=1N957:130V	31a	-	-

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1N989	Z-Di	=1N957:150V	31a	-	-
1N99(A)	Ge-Di	Uni,80V,30mA,A:92V	31a	USA,Tho	AA117..118,AA132..133
1N990	Z-Di	=1N957:160V	31a	-	-
1N991	Z-Di	=1N957:180V	31a	-	-
1N991B	Z-Di	180V,0.5W,Zzt=2200Ω	-	Fairchild	-
1N992	Z-Di	=1N957:200V	31a	-	-
1N993	Si-Di	SS,20V,0,02A,<1pF,<4ns	31a	USA	BA218,BAX13,BAX91,1N4148..49,+
1N994	Ge-Di	SS,6,5V,0,02A,<2ns	31a	USA	-
1N995	Ge-Di	SS,10V,0,03A,<0,7pF,<6ns	31a	USA	-
1N996	Ge-Di	S,20V,0,05A,<300ns	31a	USA	AAY27..28,1N631,1N633,1N3592
1N997	Si-Di	S,35V,0,05A,150ns	31a	USA	BAX85,BAX89..90,BAX94,1N4148,+
1N998	Si-Di	GI,Uni,150V	31a	USA	BA157..159,BA194,BAS11,BAW52,+
1N999	Si-Di	SS,100V,<2pF,<4ns	31a	USA	BA219,BAX96
1NE11	Si-Di	GI,S,contr.av.,1000V,1A,1kW(10?s)	34a$	Tos	BYD13M,BYD33M,BYV26E,1N4249,+
1NH61	Si-Di	GI,Uni,1000V,0,3A,<6?s	31a	Tos	BA159,BY527,BYD11M,1N4007,+
1NU41	Si-Di	GI,S,1000V,1A,<100ns	31a	Tos	BYT11/1000,BYV26E
1NZ61	Si-Di	GI,Uni,1000V,1A	31a	Tos	BY127,BY133,BY227,1N4007,+
10...1R					
10	Si-N	=2SD2359(Typ-Code/Stempel/marking)	39	Mat	→2SD2359
10	N-FET	=2SK198(Typ-Code/Stempel/marking)	35	Mat	→2SK198
10	N-FET	=2SK662(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK662
10P	N-FET	=2SK198-P(Typ-Code/Stempel/marking)	35	Mat	→2SK198
10P	N-FET	=2SK662-P(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK662
10Q	N-FET	=2SK198-Q(Typ-Code/Stempel/marking)	35	Mat	→2SK198
10Q	N-FET	=2SK662-Q(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK662
10R	N-FET	=2SK198-R(Typ-Code/Stempel/marking)	35	Mat	→2SK198
10R	N-FET	=2SK662-R(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK662
10s	Si-N/P	=BC846PN(Typ-Code/Stempel/marking)	46(2mm)	Sie	→BC846PN
10s	Si-N/P	=BC846UPN(Typ-Code/Stempel/marking)	46	Sie	→BC846UPN
1P	Si-N	=FMMT2222A(Typ-Code/Stempel/marking)	35	Fer	→FMMT2222A
1P	Si-N	=KST2222A(Typ-Code/Stempel/marking)	35	Sam	→KST2222A
1P	Si-N	=MMBT2222A(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT2222A
1P	Si-N	=MMBT2222AT(Typ-Code/Stempel/marking	35(1,6mm)	Ons	→MMBT2222AT
1P	Si-N	=MMBT2222AW(Typ-Code/Stempel/marking)	35(2mm)	Ons	→MMBT2222AW
1P	Si-N	=YTS2222A(Typ-Code/Stempel/marking)	35	Tos	→YTS2222A
-1P	Si-N	=PMST2222A(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST2222A
1P137	Si-P+R	=RT1P137L(Typ-Code/Stempel/marking)	7(9mm)	Mit	→RT1P137L
1P643	Si-Di	GI,S,50V,1A,2pF,<500ns	31a	Itt,Fag	BY201/2,BYX55/350,RGP10A,+
1P644	Si-Di	=1P643:100V	31a	-	BY201/2,BYX55/350,RGP10B,+
1P645	Si-Di	=1P643:225V	31a	-	BY201/3,BYX55/350,RGP10G,+
1P646	Si-Di	=1P643:300V	31a	-	BY201/3,BYX55/350,RGP10G,+
1P647	Si-Di	=1P643:400V	31a	-	BY201/4,BYX55/600,RGP10G,+
1P648	Si-Di	=1P643:500V	31a	-	BY201/5,BYX55/600,RGP10J,+
1P649	Si-Di	=1P643:600V	31a	-	BY201/6,BYX55/600,RGP10J,+
1P664	Si-Di	?BY201/12	31a	-	→BY201/12
1PMT5.0A..58A(T3)..	Z-Di	SMD,TAZ,5..58V,5%,175W(1ms)	71a(2mm)	Ons	-
1PMT5920B..5941B .	Z-Di	SMD,6,2..47V,5%,0,5W	71a(2mm)	Ons	-
1Ps	Si-N/P	=BC847PN(Typ-Code/Stempel/marking)	46(2mm)	Sie	→BC847PN
1PS181	Si-Di	=1PS193:Dual	35m	Phi	-
1PS184	Si-Di	=1PS193:Dual	35l	Phi	-
1PS193	Si-Di	SMD,SS,80V,0,215A,<4ns	35e	Phi	-
1PS226	Si-Di	=1PS193:Dual	35o	Phi	-
1PS300	Si-Di	SMD,Dual,SS,85V,2x85mA,<4ns	35m(2mm)	Phi	1SS300
1PS301	Si-Di	=1PS300:2x80mA	35l(2mm)	-	1SS301
1PS302	Si-Di	=1PS300:	35o(2mm)	-	1SS302
1PS59SB10	Si-Di	SMD,Schottky,SS,30V,0,2A,<5ns	35e	Phi	MA721
1PS59SB14	Si-Di	=1PS59SB10:Dual	35o	-	-
1PS59SB15	Si-Di	=1PS59SB10:Dual	35l	-	MA721WK
1PS59SB16	Si-Di	=1PS59SB10:Dual	35m	-	MA721WA
1PS59SB20	Si-Di	SMD,Schottky,S,40V,0,5A	35e	Phi	MA720
1PS59SB21	Si-Di	SMD,Schottky,S,40V,0,2A	35e	Phi	MA720
1PS70SB10	Si-Di	SMD,Schottky,S,30V,0,2A	35e(2mm)	Phi	-
1PS70SB14	Si-Di	=1PS70SB14:Dual	35o(2mm)	-	-

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1PS70SB15	Si-Di	=1PS70SB15:Dual	35l(2mm)	-	-
1PS70SB16	Si-Di	=1PS70SB16:Dual	35m(2mm)	-	-
1PS70SB20	Si-Di	-	35e	Philips	-
1PS70SB40	Si-Di	SMD,Schottky,SS,40V,0,12A	35e(2mm)	Phi	-
1PS70SB44	Si-Di	=1PS70SB40:Dual	35o(2mm)	-	-
1PS70SB45	Si-Di	=1PS70SB40:Dual	35l(2mm)	-	-
1PS70SB46	Si-Di	=1PS70SB40:Dual	35m(2mm)	-	-
1PS70SB82	Si-Di	-	35e(2mm)	Philips	-
1PS70SB84	Si-Di	-	35o(2mm)	Philips	-
1PS70SB85	Si-Di	-	35l(2mm)	Philips	-
1PS70SB86	Si-Di	-	35m(2mm)	Philips	-
1PS74SB23	Si-Di	SMD,Schottky,S,25V,1A	46	Phi	-
1PS75SB45	Si-Di	SMD,Dual,Schottky,SS,40V,0,12A	35l(1,6mm)	Phi	-
1PS76SB10	Si-Di	SMD,Schottky,SS,30V,0,2A,<5ns	71a(1,7mm)	Phi	BAT54J
1PS76SB17	Si-Di	SMD,Schottky,UHF-M,4V,30mA	71a(1,7mm)	Phi	HSU276
1PS76SB21	Si-Di	SMD,Schottky,S,40V,0,2A	71a(1,7mm)	Phi	RB500V-40,RB501V-40,1SS357
1PS76SB40	Si-Di	SMD,Schottky,S,40V,0,12A	71a(1,7mm)	Phi	BAS140W
1PS76SB70	Si-Di	SMD,6chottky,S,70V,0,07A	71a(1,7mm)	Phi	BAS70J,BAS170W
1PS79SB10	Si-Di	SMD,Schottky,SS,30V,0,2A	71a(1,3mm)	Phi	MA2S784
1PS79SB40	Si-Di	SMD,Schottky,S,40V,0,12A	71a(1,3mm)	Phi	1SS369,1SS388
1PS79SB70	Si-Di	SMD,Schottky,S,70V,0,07A	71a(1,3mm)	Phi	-
1PS88SB48	Si-Di	SMD,Quad,Schottky,S,40V,0,12A	46bk(2mm)	Phi	-
1PS89SB14	Si-Di	SMD,Dual,Schottky,S,30V,0,2A	35o(1,6mm)	Phi	-
1PS89SB15	Si-Di	=1PS89SB14:	35l(1,6mm)	Phi	-
1PS89SB16	Si-Di	=1PS89SB14:	35m(1,6mm)	Phi	-
1PS89SS04	Si-Di	SMD,Dual,SS,85V,0,2A,<4ns	35o(1,6mm)	Phi	-
1PS89SS05	Si-Di	=1PS89SS04:	35l(1,6mm)	Phi	-
1PS89SS06	Si-Di	=1PS89SS04:	35m(1,6mm)	Phi	-
1Q	Si-N	=KST5088(Typ-Code/Stempel/marking)	35	Sam	→KST5088
1Q	Si-N	=MMBT5088(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT5088
-1Q	Si-N	=PMST5088(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST5088
1Q4B42	Si-Br	1200V,1A	?4-DIP	Tos	B1000C1000(DIP)
1QE11	Si-Di	Gl,S,contr.av.,1200V,1A,1kW(10?s)	34a$	Tos	BYD33U
1QZ61	Si-Di	Gl,Uni,1200V,1A	31a	Tos	BY127,BY133,BY227,GP10Q,+
1R	Si-P	=2SB970(Typ-Code/Stempel/marking)	35	Mat	→2SB970
1R	Si-N	=2SC4929(Typ-Code/Stempel/marking)	39	Mat	→2SC4929
1R	Si-N	=KST5089(Typ-Code/Stempel/marking)	35	Sam	→KST5089
1R	Si-N	=MMBT5089(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT5089
-1R	Si-N	=PMST5089(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST5089
1RSBL41	Si-Di	Gl,S,100V,1,5A,<100ns	31a	Tos	BYD73B..G,BYV27/100,BYV36A..E,+
1RSBZ41	Si-Di	Gl,Uni,100V,1,5A	31a	Tos	BYD14D..M,BYX82..87,1N5392..99,+
1RSBZ61	Si-Di	Gl,Uni,100V,1,5A	31a	Tos	BYD14D..M,BYX82..87,1N5392..99,+
1RSCL41	Si-Di	Gl,S,150V,1,5A,<100ns	31a	Tos	BYD73C..G,BYV27/150,BYV36A..E,+
1RSDL41	Si-Di	Gl,S,200V,1,5A,<100ns	31a	Tos	BYD73D..G,BYV27/200,BYV36A..E,+
1RSDU41	Si-Di	Gl,S,200V,1,5A,<100ns	31a	Tos	BYD73D..G,BYV27/200,BYV36A..E,+
1RSDZ41	Si-Di	Gl,Uni,200V,1,5A	31a	Tos	BYD14D..M,BYX82..87,1N5393..99,+
1RSDZ61	Si-Di	Gl,Uni,200V,1,5A	31a	Tos	BYD14D..M,BYX82..87,1N5393..99,+
1RSGU41	Si-Di	Gl,S,400V,1,5A,<100ns	31a	Tos	BYD73G,BYV36B..E,EGP20G,FE2H
1RSGZ41	Si-Di	Gl,Uni,400V,1,5A	31a	Tos	BYD14G..M,BYX83..87,1N5395..99,+
1RSGZ61	Si-Di	Gl,Uni,400V,1,5A	31a	Tos	BYD14G..M,BYX83..87,1N5395..99,+
1RSJZ61	Si-Di	Gl,Uni,600V,1,5A	31a	Tos	BYD14J..M,BYX84..87,1N5397..99,+
1RSNU41	Si-Di	Gl,S,1000V,1,5A,<100ns	31a	Tos	BYM26E,BYT56M
1RSTH61	Si-Di	Gl,Uni,1500V,1A,<20?s	31a	Tos	BY350/1000,BY448,GP10W,GH3F
1RM150	Si-Di	=1RM40:15kV	-		-
1RM250	Si-Di	=1RM40:25kV	-		-
1RM40	Si-Di	kV-Gl,4kV,0,5A	-	Tho	-
1RM80	Si-Di	=1RM40:8kV	-		-
1RQ	Si-P	=2SB1585-Q(Typ-Code/Stempel/marking)	?35	Mat	→2SB1585
1RQ	Si-P	=2SB970-Q(Typ-Code/Stempel/marking)	35	Mat	→2SB970
1RR	Si-P	=2SB1585-R(Typ-Code/Stempel/marking)	?35	Mat	→2SB1585
1RR	Si-P	=2SB970-R(Typ-Code/Stempel/marking)	35	Mat	→2SB970
1RS	Si-P	=2SB1585-S(Typ-Code/Stempel/marking)	?35	Mat	→2SB1585
1RS	Si-P	=2SB970-S(Typ-Code/Stempel/marking)	35	Mat	→2SB970

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1S					
1S	Si-N	=2SC3130(Typ-Code/Stempel/marking)	3S	Mat	→2SC3130
1S	Si-N	=2SC3935(Typ-Code/Stempel/marking)	3S(2mm)	Mat	→2SC3935
1S	Si-N	=2SC4809(Typ-Code/Stempel/marking)	3S(1,6mm)	Mat	→2SC4809
1S	Si-N	=2SD2413(Typ-Code/Stempel/marking)	39	Mat	→2SD2413
1S	Si-N	=MMBT2369A(Typ-Code/Stempel/marking)	3S	Nsc	→MMBT2369A
1S020	Si-Di	Gl,100V,1,5A	34a$	Tix	BY251..255,BY226..227,1N5392..99,+
1S021	Si-Di	=1S020:200V	34a$	Tix	BY251..255,BY226..227,1N5393..99,+
1S023	Si-Di	=1S020:400V	34a$	Tix	BY252..255,BY226..227,1N5395..99,+
1S025	Si-Di	=1S020:600V	34a$	Tix	BY253..255,BY226..227,1N5397..99,+
1S027	Si-Di	=1S020:800V	34a$	Tix	BY254..255,BY227,1N5398..99,+
1S100	Si-Di	Gl,150V,0,75A	34a$	Tix,Tos	BY126..127,BY133..135,1N4003..07,+
1S1000(A)	Si-Di	UHF-M,890MHz	31a	Njr	-
1S1001	Ge-Di	S,20V,0,05A,<200ns	31a	Njr	AAY28,1N631,1N633
1S1002	Ge-Di	S,25V,0,1A,<300ns	31a	Njr	AAY49,AAZ15,AAZ17
1S1003	Ge-Di	Uni,125V,0,075A	31a	Njr	AA133,1N634..635
1S1004	Ge-Di	Uni,100V,0,05A	31a	Njr	AA117..118,AA132..133
1S1005	Ge-Di	Uni,100V,0,05A	31a	Njr	AA117..118,AA132..133
1S1006	Ge-Di	Uni,60V,0,05A	31a	Njr	AA117..118,AA132..133
1S1007	Ge-Di	Uni,60V,0,075A	31a	Njr	AA117..118,AA132..133
1S1008	Ge-Di	Uni,25V,0,08A	31a	Njr	AA117..118,AA132..134,1N60,+
1S1009	Ge-Di	Uni,25V,0,05A	31a	Njr	AA117..118,AA132..134,1N60,+
1S100R...109R	Si-Di	=1S100..109:	34b&	-	→1S100..109
1S100R..109R	Si-Di	-	34b&	-	-
1S101	Si-Di	=1S100:200V	34a$	-	BY126..127,BY133..134,1N4003..07,+
1S1010	Ge-Di	Uni,30V,0,05A	31a	Njr	AA117..118,AA132..134,1N60,+
1S1011(L,S)	Si-St	0,2..0,35V,0,05W	31a	Njr	-
1S1012	Si-Di	?1S871	31a	Org	→1S871
1S1013	Si-Di	?1S871A	31a	Org	→1S871A
1S1014	Si-Di	?1S871B	31a	Org	→1S871B
1S1015	Si-Di	?1S871C	31a	Org	→1S871C
1S1016	Si-Di	?1S871D	31a	Org	→1S871D
1S1017	Si-Di	?1S871E	31a	Org	→1S871E
1S1018	Si-Di	?1S871F	31a	Org	→1S871F
1S1019	Si-Di	?1S871G	31a	Org	→1S871G
1S102	Si-Di	=1S100:300V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S1020	Si-Di	?1S871H	31a	Org	→1S871H
1S1021	Si-Di	?1S881	36a	Org	→1S881
1S1022	Si-Di	?1S881A	36a	Org	→1S881A
1S1023	Si-Di	?1S881B	36a	Org	→1S881B
1S1024	Si-Di	?1S881C	36a	Org	→1S881C
1S1025	Si-Di	?1S881D	36a	Org	→1S881D
1S1026	Si-Di	?1S881E	36a	Org	→1S881E
1S1027	Si-Di	?1S881	31a	Org	→1S881
1S1028	Si-Di	?1S881A	31a	Org	→1S881A
1S1029	Si-Di	?1S881B	31a	Org	→1S881B
1S103	Si-Di	=1S100:400V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S1030	Si-Di	?1S881C	31a	Org	→1S881C
1S1031	Si-Di	?1S881D	31a	Org	→1S881D
1S1032	Si-Di	?1S881E	31a	Org	→1S881E
1S1033	Si-Di	Gl-L,200V,200A(Tc=110o)	73b&	Org	-
1S1034	Si-Di	=1S1033:300V	73b&	-	-
1S1035	Si-Di	=1S1033:400V	73b&	-	-
1S1036	Si-Di	=1S1033:600V	73b&	-	-
1S1037	Si-Di	=1S1033:800V	73b&	-	-
1S1038	Si-Di	=1S1033:1000V	73b&	-	-
1S1039	Si-Di	Gl,400V,1,5A	-		(BY205/400,BY252..255,BYX49/600,++)
1S104	Si-Di	=1S100:500V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S1040	Si-Di	=1S1039:600V	-		(BY205/600,BY253..255,BYX49/600,++)
1S1041	Si-Di	=1S1039:800V	-		(BY205/800,BY254..255,BYX49/900,++)
1S1042	Si-Di	=1S1039:1000V	-		(BY205/1000,BY255,BYX49/1000,++)
1S1043	Si-Di	Gl,400V,0,75A	34	Org	BY126..127,BY133..134,1N4004..07,+
1S1044	Si-Di	=1S1043:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S1045	Si-Di	=1S1043:800V	34	-	BY127,BY133,BY227,1N4006..07,+

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1S1046	Si-Di	=1S1043:1000V	34	-	BY127,BY133,BY227,1N4007,+
1S1047	Si-Di	=1S1043:1200V	34	-	BY127,BY133,BY227,GP10Q,+
1S1048	Si-Di	=1S1043:1400V	34	-	BY400,BY448,DM513,GP10V,+
1S1049	Si-Di	=1S1043:1600V	34	-	BY400,DM513,EM516,GP10Y
1S105	Si-Di	=1S100:600V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S1050	Si-Di	=1S1043:1800V	34	-	DM516
1S1051	Si-Di	=1S1043:2000V	34	-	-
1S1052	Si-Di	GI-L,300V,3A	?32a$	Org	BYX38/300,BYX39/600
1S1052R..1059R..	Si-Di	=1S1052..1059:	?32b&	-	BYX38/..R,BYX39/..R
1S1052R..1059R...	Si-Di	-	?32b&	-	BYX38/..R,BYX39/..R
1S1053	Si-Di	=1S1052:400V	?32a$	-	BYX38/600,BYX39/600
1S1054	Si-Di	=1S1052:600V	?32a$	-	BYX38/600,BYX39/600
1S1055	Si-Di	=1S1052:800V	?32a$	-	BYX38/900,BYX39/900
1S1056	Si-Di	=1S1052:1000V	?32a$	-	BYX38/1200,BYX39/1000
1S1057	Si-Di	=1S1052:1200V	?32a$	-	BYX38/1200,BYX39/1200
1S1058	Si-Di	=1S1052:1400V	?32a$	-	BYX39/1400
1S1059	Si-Di	=1S1052:1600V	?32a$	-	-
1S106	Si-Di	=1S100:700V	34a$	-	BY127,BY133,BY227,1N4006..07,+
1S1061	Si-Di	=1S1043:100V,1A	31a	Org	→1S1043
1S1062	Si-Di	=1S1043:200V,1A	31a	-	→1S1043
1S1063	Si-Di	=1S1043:1A	31a	-	→1S1043
1S1064	Si-Di	=1S1044:1A	31a	-	→1S1044
1S1065	Si-Di	=1S1045:1A	31a	-	→1S1045
1S1066	Si-Di	=1S1046:1A	31a	-	→1S1046
1S1067	Si-Di	=1S1047:1A	31a	-	→1S1047
1S1068	Si-Di	=1S1048:1A	31a	-	→1S1048
1S1069	Si-Di	=1S1049:1A	31a	-	→1S1049
1S107	Si-Di	=1S100:800V	34a$	-	BY127,BY133,BY227,1N4006..07,+
1S1070	Si-Di	=1S1050:1A	31a	-	→1S1050
1S1071	Si-Di	GI,100V,1,5A	31a	Org	BY226..228,BY251..255,1N5392..99,+
1S1072	Si-Di	=1S1071:200V	31a	-	BY226..228,BY251..255,1N5393..99,+
1S1073	Si-Di	=1S1071:400V	31a	-	BY226..228,BY252..255,1N5395..99,+
1S1074	Si-Di	=1S1071:600V	31a	-	BY226..228,BY253..255,1N5397..99,+
1S1075	Si-Di	=1S1071:800V	31a	-	BY227..228,BY254..255,1N5398..99,+
1S1076	Si-Di	=1S1071:1000V	31a	-	BY227..228,BY255,BYW17/1000,1N5399,+
1S1077	Si-Di	=1S1071:1200V	31a	-	BY227..228,BY255,BYW17/1200,+
1S1078	Si-Di	=1S1071:1400V	31a	-	BY228,BY400,BY448
1S1079	Si-Di	=1S1071:1600V	31a	-	BY400
1S108	Si-Di	=1S100:900V	34a$	-	BY127,BY133,BY227,1N4007,+
1S1080	Si-Di	=1S1071:1800V	31a	-	-
1S1081	Si-Di	GI,200V,3A	?32	Org	BYX38/300,BYX39/600
1S1083	Si-Di	GI-L,200V,55A	-	Org	-
1S1084	Si-Di	=1S1083:300V	-		-
1S1085	Si-Di	=1S1083:400V	-		-
1S1086	Si-Di	=1S1083:500V	-		-
1S1087	Si-Di	=1S1083:600V	-		-
1S1088	Si-Di	=1S1083:700V	-		-
1S1089	Si-Di	=1S1083:800V	-		-
1S109	Si-Di	=1S100:1000V	34a$	-	BY127,BY133,BY227,1N4007,+
1S1090	Si-Di	=1S1083:1000V	-		-
1S1091	Si-Di	=1S1083:1200V	-		-
1S1092	Si-Di	=1S1083:1400V	-		-
1S1093	Si-Di	=1S1083:1600V	-		-
1S1094	Z-Di	6,2..8V,0,2W	31a	Org	BZX55/..,BZX79/..,ZPD..,1N5234..60,+
1S1095	Z-Di	=1S1094:7,5..10V	31a	-	-
1S1096	Z-Di	=1S1094:9..12V	31a	-	-
1S1097	Z-Di	=1S1094:11..14,5V	31a	-	-
1S1098	Z-Di	=1S1094:13,5..18V	31a	-	-
1S1099	Z-Di	=1S1094:17..21V	31a	-	-
1S11	Ge-Di	Dem,60V,50mA	31a	Mat	AA113,1N34,1N60
1S110	Si-Di	Dual,GI,500V,0,4A	-	Tos	(2xBY126..127,2xBY133..134,++)
1S1100	Z-Di	=1S1094:20..27V	31a	-	-
1S1101	Z-Di	=1S1094:25..32V	31a	-	-
1S1102	Z-Di	=1S1094:30..42V	31a	-	-

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1S1103	Si-Di	kV-Gl,8kV,0,15A	31	Org	SMH-08
1S1104	Si-Di	=1S1103:10kV	31	Org	SMH-10
1S1105	Si-Di	=1S1103:16kV	31	Org	SMH-16
1S1106	Si-Di	=1S1103:20kV	31	Org	RMH-20
1S1107	Si-Di	kV-Gl,8kV,0,15A	-	Org	-
1S1108	Si-Di	=1S1107:10kV	-		-
1S1109	Si-Di	=1S1107:16kV	-		-
1S111	Si-Di	-	34a$	NEC	BY126..127,BY133..135,1N4002..07,+
1S111[Japan]	Si-Di	Gl,100V,0,75A	34a$	Nec	BY126..127,BY133..135,1N4002..07,+
1S111[Texas]	Si-Di	Gl,225V,0,4A	31a	Tix	BA157..159,BY204/4,1N4004..07,+
1S1110	Si-Di	=1S1107:20kV	-		-
1S1111	Si-Di	kV-Gl,8kV,0,15A	-	Org	SMHD2-08
1S1112	Si-Di	=1S1111:10kV	-	Org	SMHD2-10
1S1113	Si-Di	=1S1111:16kV	-	Org	SMHD2-16
1S1114	Si-Di	=1S1111:20kV	-	Org	SMHD2-20
1S1115	Si-Di	kV-Gl,8kV,0,5A	-	Org	-
1S1116	Si-Di	=1S1115:10kV	-		-
1S1117	Si-Di	kV-Gl,8kV,0,5A	-	Org	-
1S1118	Si-Di	=1S1117:10kV	-		-
1S1119	Si-Di	=1S1117:16kV	-		-
1S112	Si-Di	-	31a	TI	BA157..159,BY204/4,1N4004..07,+
1S112[Japan]	Si-Di	=1S111[Japan]:200V	34a$	Nec	BY126..127,BY133..134,1N4003..07,+
1S112[Texas]	Si-Di	=1S111[Texas]:300V	31a	Tix	BA157..159,BY204/4,1N4004..07,+
1S1120	Si-Di	=1S1117:20kV	-		-
1S1121	Si-Br	Gl,100V,0,3A	?79	Org	B100C300,etc.
1S1122	Si-Br	=1S1121:200V	?79	-	B200C300,etc.
1S1123	Si-Br	=1S1121:300V	?79	-	B300C300,etc.
1S1124	Si-Br	=1S1121:400V	?79	-	B400C300,etc.
1S1125	Si-Br	=1S1121:600V	?79	-	B600C300,etc.
1S1126	Si-Br	=1S1121:800V	?79	-	B800C300,etc.
1S1127	Si-Br	=1S1121:1000V	?79	-	B1000C300,etc.
1S1128	Si-Br	Gl,100V,0,3A	-	Org	B100C300,etc.
1S1129	Si-Br	=1S1128:200V	-		B200C300,etc.
1S113	Si-Di	-	34a$	NEC	BY126..127,BY133..134,1N4004..07,+
1S113[Japan]	Si-Di	=1S111[Japan]:300V	34a$	Nec	BY126..127,BY133..134,1N4004..07,+
1S113[Texas]	Si-Di	=1S111[Texas]:400V	31a	Tix	BA157..159,BY204/4,1N4004..07,+
1S1130	Si-Br	=1S1128:300V	-		B300C300,etc.
1S1131	Si-Br	=1S1128:400V	-		B400C300,etc.
1S1132	Si-Br	=1S1128:600V	-		B600C300,etc.
1S1133	Si-Br	=1S1128:800V	-		B800C300,etc.
1S1134	Si-Br	=1S1128:1000V	-		B1000C300,etc.
1S1135	Si-Br	Gl,100V,1A	-	Org	B100C1000,etc.
1S1136	Si-Br	=1S113S:200V	-		B200C1000,etc.
1S1137	Si-Br	=1S1135:300V	-		B300C1000,etc.
1S1138	Si-Br	=1S1135:400V	-		B400C1000,etc.
1S1139	Si-Br	=1S1135:600V	-		B600C1000,etc.
1S114	Si-Di	-	34a$	NEC	BY126..127,BY133..134,1N4004..07..
1S114[Japan]	Si-Di	=1S111[Japan]:400V	34a$	Nec	BY126..127,BY133..134,1N4804..07,+
1S1140	Si-Br	=1S1135:800V	-		B800C1000,etc.
1S1141	Si-Br	=1S1135:1000V	-		B1000C1000,etc.
1S1144	Si-Di	S,90V,0,4A,<20ns	2c	Oki	BAV14..16
1S1145	Si-Di	S,90V,0,9A,<20ns	34a	Oki	-
1S1146	Si-Di	SS,40V,0,1A,<6,9ns	31a	Hit	BAW62,BAX95,1N4148..49,1N4151,+
1S1147	Si-Di	SS,40V,0,045A,<6,9ns	31a	Hit	BAW62,BAX95,1N4148..49,1N4151,+
1S1148	Si-Di	SS,60V,0,25A,<7ns	31a	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S1149	Si-Di	SS,70V,0,25A,<7ns	31a	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S1115[Japan]	Si-Di	=1S111[Japan]:500V	34a$	Nec	BY126..127,BY133..134,1N4005..07,+
1S1115[Texas]	Si-Di	=1S111[Texas]:600V	31a	Tix	BA158..159,BY204/8,1N4005..07,+
1S1150	Si-Di	Gl-L,400V,280A(Tc=110o)	73b&	Fjd	-
1S1151	Si-Di	=1S1150:800V	73b&	-	-
1S1152	Si-Di	=1S1150:1000V	73b&	-	-
1S1153	Si-Di	=1S1150:1200V	73b&	-	-
1S1154	Z-Di	6,3..7,7V,0,1W	2	Nec	BZX55/..,BZX79/..,ZPD..,1N5234..41,+
1S1155	Z-Di	=1S1154:7,5..9V	2	-	-

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1S1156	Z-Di	=1S1154:8,8..10,8V	2	-	-
1S116	Si-Di	-	34a$	NEC	BY126..127,BY133..134,1N4005..07..
1S116[Japan]	Si-Di	=1S111[Japan]:600V	34a$	Nec	BY126..127,BY133..134,1N4005..07,+
1S1160	Z-Di	3..4,5V,0,2W	31a	Nec	BZX55/..,BZX79/..,ZPD..,1N5225..60,+
1S1161	Z-Di	=1S1160:4,3..5,4V	31a	-	-
1S1162	Z-Di	=1S1160:5,2..6,4V	31a	-	-
1S1163	Z-Di	=1S1160:6,2..8V	31a	-	-
1S1164	Z-Di	=1S1160:7,5..10V	31a	-	-
1S1165	Z-Di	=1S1160:9..12V	31a	-	-
1S1166	Z-Di	=1S1160:11..14,5V	31a	-	-
1S1167	Z-Di	=1S1160:13,5..18V	31a	-	-
1S1168	Z-Di	=1S1160:17..21V	31a	-	-
1S1169	Z-Di	=1S1160:20..27V	31a	-	-
1S117[Japan]	Si-Di	=1S111[Japan]:700V	34a$	Nec	BY127,BY133,BY227,1N4006..07,+
1S117[Texas]	Si-Di	=1S111[Texas]:800V	31a	Tix	BA159,BY204/8,1N4006..07,+
1S1170	Z-Di	=1S1160:25..32V	31a	-	-
1S1171	Z-Di	=1S1160:30..42V	31a	-	-
1S1172	Z-Di	4,3..5,4V,1W	34	Nec	BZW22/..,BZX61/..,ZPY..,1N5916..43,+
1S1173	Z-Di	=1S1172:5,2..6,4V	34	-	-
1S1174	Z-Di	=1S1172:6,2..8V	34	-	-
1S1175	Z-Di	=1S1172:7,5..10V	34	-	-
1S1176	Z-Di	=1S1172:9..12V	34	-	-
1S1177	Z-Di	=1S1172:11..14,5V	34	-	-
1S1178	Z-Di	=1S1172:13,5..18V	34	-	-
1S1179	Z-Di	=1S1172:17..21V	34	-	-
1S118	Si-Di	-	34a$	NEC	BY127,BY133,BY227,1N4006..07..
1S118[Japan]	Si-Di	=1S111[Japan]:800V	34a$	Nec	BY127,BY133,BY227,1N4006..07,+
1S1180	Z-Di	=1S1172:20..27V	34	-	-
1S1181	Z-Di	=1S1172:25..32V	34	-	-
1S1182	Z-Di	=1S1172:30..40V	34	-	-
1S1183	Z-Di	=1S1172:38,5..47,5V	34	-	-
1S1184	Z-Di	=1S1172:45,5..57V	34	-	-
1S1185	Z-Di	4,3..5,4V,3W	32	Nec	BZX98/..,BZY93..,ZX..,1N2970..99
1S1186	Z-Di	=1S1185:5,2..6,4V	32	-	-
1S1187	Z-Di	=1S1185:6,2..8V	32	-	-
1S1188	Z-Di	=1S1185:7,5..10V	32	-	-
1S1189	Z-Di	=1S1185:9..12V	32	-	-
1S119	Si-Di	-	34a$	NEC	BY126..127,BY133..135,1N4001..07..
1S119[Japan]	Si-Di	=1S111[Japan]:50V	34a$	Nec	BY126..127,BY133..135,1N4001..07,+
1S1190	Z-Di	=1S1185:11..14,5V	32	-	-
1S1191	Z-Di	=1S1185:13,5..18V	32	-	-
1S1192	Z-Di	=1S1185:17..21V	32	-	-
1S1193	Z-Di	=1S1185:20..27V	32	-	-
1S1194	Z-Di	=1S1185:25..32V	32	-	-
1S1195	Z-Di	=1S1185:30..40V	32	-	-
1S1196	Z-Di	=1S1185:38,5..47,5V	32	-	-
1S1197	Z-Di	=1S1185:49,5..57V	32	-	-
1S1198(A)	Ge-Di	Tunnel-Di,SS	?31	Nec	-
1S1199(A)	Ge-Di	Tunnel-Di,SS	?31	Nec	-
1S12	Ge-Di	Dem,22,5V,50mA	31a	Mat	AA112..114,1N34,1N54,1N60,+
1S120[Japan]	Si-Di	Gl,50V,0,6A	34a$	Nec	BY126..127,BY133..135,1N4001..07,+
1S120[Texas]	Si-Di	Gl,50V,0,2A	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1200(A)	Ge-Di	Tunnel-Di,SS	?31	Nec	-
1S1201(H)	Z-Di	5,9..6,5V,0,25W	2	Hit	-
1S1202(H)	Z-Di	=1S1201:6,2..8V	2	-	-
1S1203	Ref-Di	8..8,8V	-	Hit	-
1S1207	Si-Di	Gl-L,contr.av.,1000V,10A(Tc=120o)	32a$	Nec	1N4510..11
1S1208	Si-Di	Uni,100V,0,2A	31a	Nec	BA188..190,BAY19..21,BAY45..46,+
1S1209	Si-St	0,63..0,69V(10mA),0,1W	31a	Nec	BA220,BZ102/0V7,BZX55/C0V8,ZPD1
1S121[Japan]	Si-Di	=1S120[Japan]:100V	34a$	Nec	BY126..127,BY133..135,1N4002..07,+
1S121[Texas]	Si-Di	=1S120[Texas]:150V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1210	Si-St	0,56..0,61V(1,5mA),0,06W	31a	Nec	-
1S1211	Si-St	0,59..0,64V(1,5mA),0,06W	31a	Nec	-
1S1212	Si-St	0,62..0,67V(1,5mA),0,06W	31a	Nec	BA220,BZ102/0V7,BZX55/C0V8,ZPD1

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1S1213	Ge-Di	S, Uni, 50V, 0,06A, <250ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1214	Ge-Di	S, Uni, 50V, 0,06A, <250ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1215	Ge-Di	S, Uni, 40V, 0,06A, <200ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1216	Ge-Di	S, Uni, 30V, 0,06A, <150ns	31a	Nec	AAZ15, AAZ17, 1N276
1S1217	Ge-Di	S, Uni, 75V, 0,1A, <750ns	31a	Nec	AAZ15
1S1218	Ge-Di	S, Uni, 100V, 0,1A, <750ns	31a	Nec	AAZ15
1S1219(H)	Si-Di	SS, 30V, 0,1A, <4ns	31a	Hit	BA317, BAY71, 1N4148..49, 1N4151, +
1S122	Si-Di	-	34a$	NEC	BY126..127, BY133..134, 1N4003..07..
1S122[Japan]	Si-Di	=1S120[Japan]: 200V	34a$	Nec	BY126..127, BY133..134, 1N4003..07, +
1S1220(H)	Si-Di	SS, 30V, 0,3A, <4ns	31a	Hit	BAW76
1S1221	Si-Di	GI, Uni, 200V, 0,5A	31a	Shi	BY126..127, BY133..134, 1N4003..07, +
1S1222	Si-Di	=1S1221: 600V	31a	-	BY126..127, BY133..134, 1N4005..07, +
1S1223	Si-Di	=1S1221: 1000V	31a	-	BY127, BY133, BY227, 1N4007, +
1S1224	Si-Di	GI, Uni, 600V, 0,1A	31a	Shi	BA158..159, BAY89..91, BY203/12, +
1S1225	Si-Di	=1S1224: 800V	31a	-	BA158..159, BAY90..91, BY203/12, +
1S1225A	Si-Di	=1S1224: 1000V	31a	-	BA159, BAY90..91, BY203/12, SHG1, +
1S1226	Si-Di	=1S1224: 1500V	31a	-	BAY91, BY203/16, BY584, SHG1,5, +
1S123	Si-Di	-	34a$	-	BY126..127, BY133..134, 1N4004..07..
1S123[Japan]	Si-Di	=1S120[Japan]: 300V	34a$	-	BY126..127, BY133..134, 1N4004..07, +
1S1230(H,N)	Si-Di	GI, Uni, 400V, 0,5A	34	Hit	BY126..127, BY133..134, 1N4004..07, +
1S1231(H,N)	Si-Di	=1S1230: 500V	34	-	BY126..127, BY133..134, 1N4005..07, +
1S1232(H,N)	Si-Di	=1S1230: 600V	34	-	BY126..127, BY133..134, 1N4005..07, +
1S1233(H,N)	Si-Di	=1S1230: 800V	34	-	BY127, BY133, BY227, 1N4006..07, +
1S1234(H,N)	Si-Di	=1S1230: 1000V	34	-	BY127, BY133, BY227, 1N4007, +
1S1235	Z-Di	75..90V, 1W	34	Hit	BZW22/C82, BZX61/C82, ZPY82, 1N5947, +
1S1236	Diac	Ub=18..32V, Ib<0,2mA, Itsm=2A	31l	Tos	1N5760, N413L, D3202U
1S1237	Si-Di	Uni, S, 300V, 0,01A, <1,8?s	31a	Tos	BA147/300, BAY21, BAY46, BAY88, +
1S1238	Si-Di	=1S1237: 500V	31a	-	BA158..159, BAY89..90, BAY92, +
1S1239	Ge-Di	Dem, 25V, 0,03A	31a	Njr	AA113..114, AA119, 1N34, 1N54, 1N60, +
1S124	Si-Di	-	34a$	-	BY126..127, BY133..134, 1N4004..07..
1S124[Japan]	Si-Di	=1S120[Japan]: 400V	34a$	-	BY126..127, BY133..134, 1N4004..07, +
1S1240	Ge-Di	AFC	31a	Njr	-
1S1241	Ge-Di	AFC	31a	Njr	-
1S1242	Ge-Di	AFC	31a	Njr	-
1S1243	Ge-Di	AFC	31a	Njr	-
1S1244	Ge-Di	Dem, 22,5V, 0,05A	31a	Mat	AA112..114, AA119, 1N34, 1N54, 1N60, +
1S1245	Ge-Di	Uni, 115V, 0,05A	31a	Mat	AA117..118, AA132..133, 1N634..35
1S1246	Ge-Di	Uni, 115V, 0,05A	31a	Mat	AA117..118, AA132..133, 1N634..35
1S1247	Si-Di	GI-L, 500V, 200A(Tc=100o)	73b&	Hit	-
1S1248	Si-Di	=1S247: 600V	73b&	-	-
1S1249	Si-Di	=1S247: 800V	73b&	-	-
1S125	Si-Di	-	34a$	-	BY126..127, BY133..134, 1N4005..07..
1S125[Japan]	Si-Di	=1S120[Japan]: 500V	34a$	-	BY126..127, BY133..134, 1N4005..07, +
1S1250	Si-Di	=1S247: 1000V	73b&	-	-
1S1251	Si-Di	=1S247: 1300V	73b&	-	-
1S126	Si-Di	-	34a$	-	BY126..127, BY133..134, 1N4005..07..
1S126[Japan]	Si-Di	=1S120[Japan]: 600V	34a$	-	BY126..127, BY133..134, 1N4005..07, +
1S1260	Si-Di	GI-L, 150V, 3A	32a$	Tos	BYX38/300, BYX39/600
1S1260R...1269R..	Si-Di	=1S1260..1269:	32b&	-	BYX38/..R, BYX39/..R
1S1260R..1269R...	Si-Di	-	32b&	-	BYX38/..R, BYX39/..R
1S1261	Si-Di	=1S1260: 200V	32a$	-	BYX38/300, BYX39/600
1S1262	Si-Di	=1S1260: 300V	32a$	-	BYX38/300, BYX39/600
1S1263	Si-Di	=1S1260: 400V	32a$	-	BYX38/600, BYX39/600
1S1264	Si-Di	=1S1260: 500V	32a$	-	BYX38/600, BYX39/600
1S1265	Si-Di	=1S1260: 600V	32a$	-	BYX38/600, BYX39/600
1S1266	Si-Di	=1S1260: 700V	32a$	-	BYX38/900, BYX39/800
1S1267	Si-Di	=1S1260: 800V	32a$	-	BYX38/900, BYX39/800
1S1268	Si-Di	=1S1260: 900V	32a$	-	BYX38/900, BYX39/1000
1S1269	Si-Di	=1S1260: 1000V	32a$	-	BYX38/1200, BYX39/1000
1S127	Ge-Di	Uni, 75V, 30mA	31	Tos	AA117..118, AA132..133, 1N634
1S1270	Si-Di	GI-L, 150V, 6A	32a$	Tos	BYX38/300, BYX39/600
1S1270R...1279R..	Si-Di	=1S1270..1279:	32b&	-	BYX38/..R, BYX39/..R
1S1270R..1279R...	Si-Di	-	32b&	-	BYX38/..R, BYX39/..R
1S1271	Si-Di	=1S1270: 200V	32a$	-	BYX38/300, BYX39/600

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1S1272	Si-Di	=1S1270:300V	32a$	-	BYX38/300,BYX39/600
1S1273	Si-Di	=1S1270:400V	32a$	-	BYX38/600,BYX39/600
1S1274	Si-Di	=1S1270:500V	32a$	-	BYX38/600,BYX39/600
1S1275	Si-Di	=1S1270:600V	32a$	-	BYX38/600,BYX39/600
1S1276	Si-Di	=1S1270:700V	32a$	-	BYX38/900,BYX39/800
1S1277	Si-Di	=1S1270:800V	32a$	-	BYX38/900,BYX39/800
1S1278	Si-Di	=1S1270:900V	32a$	-	BYX38/900,BYX39/1000
1S1279	Si-Di	=1S1270:1000V	32a$	-	BYX38/1200,BYX39/1000
1S128	Ge-Di	S,6V,Ifm=0,15A,<25ns	31a	Tos	AAY48,1N995
1S1280	Si-Di	Gl-L,200V,10A	32a$	Hit	1N4525..30
1S1280R...1285R..	Si-Di	=1S1280..1285:	32b&	-	D24/400C..1200C
1S1280R..1285R...	Si-Di	-	32b&	-	D24/400C..1200C
1S1281	Si-Di	=1S1280:300V	32a$	-	1N4526..30
1S1282	Si-Di	=1S1280:400V	32a$	-	1N4526..30
1S1283	Si-Di	=1S1280:600V	32a$	-	1N4527..30
1S1284	Si-Di	=1S1280:800V	32a$	-	1N4528..30
1S1285	Si-Di	=1S1280:1000V	32a$	-	1N4529..30
1S1286	Si-Di	Gl-L,100V,15A(Tc=50o)	75a$	Tos	1N3492..95
1S1286R...1288R..	Si-Di	=1S1286..1288:	75b&	-	1N3492R..95R
1S1286R..1288R...	Si-Di	-	75b&	-	1N3492R..95R
1S1287	Si-Di	Gl-L,100V,20A(Tc=50o)	75a$	Tos	1N3492..95
1S1288	Si-Di	Gl-L,100V,20A(Tc=50o)	75a$	Tos	1N3492..95
1S1289	Si-Di	Gl-L,150V,12A	32a$	Tos	1N4525..30
1S1289R...1292R..	Si-Di	=1S1289..1292:	32b&	-	D24/C400
1S1289R..1292R...	Si-Di	-	32b&	-	D24/C400
1S129	Ge-Diode	Sw,50V,0,1A,<240nS	31a	Tos	AAY49,AAZ15,AAZ17
1S129[Japan]	Ge-Di	S,50V,0,1A,<240ns	31a	Tos	AAY49,AAZ15,AAZ17
1S1290	Si-Di	=1S1289:300V	32a$	-	1N4526..30
1S1291	Si-Di	Gl-L,150V,25A	32a$	Tos	1N4525..30
1S1292	Si-Di	=1S1291:300V	32a$	-	1N4526..30
1S1295	Si-Di	SS,70V,0,17A,<5ns	2	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S1296	Si-Di	SS,90V,0,2A,<5ns	2	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S1297	Si-Di	S,70V,0,4A,<12ns	2c	Oki	BAV14..16,BAW26..27
1S1298	Si-Di	S,125V,0,45A,<12ns	2c	Oki	BAV14..16
1S1299	Si-Di	S,125V,0,6A,<12ns	2c	Oki	BAV14..16
1S13	Ge-Di	Dem,45V,35mA	31a	Mat	AA113,1N34,1N54,1N60
1S130	Si-Di	-	31a	TI	BA157..159,BY204/4,BY206..207,+
1S130[Japan]	Ge-Di	=1S129[Japan]:<340ns	31a	Tos	AAY49,AAZ15,AAZ17
1S130[Texas]	Si-Di	Uni,50V,0,2A	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1300	Si-St	Level shift,1,65..2,2V(2mA)	31a	Hit,Nec,++	-
1S1301	Si-Di	SS,35V,0,045A,<5,3ns	31a	Hit,Nec,++	BAW62,BAX95,1N4148..49,1N4151,+
1S1302	Si-Di	SS,70V,0,25A,<7ns	31a	Hit,Nec,++	BAW62,BAX95,1N4148..49,1N4151,+
1S1303	Si-Di	SS,60V,0,25A,<7ns	31a	Hit,Nec,++	BAW62,BAX95,1N4148..49,1N4151,+
1S1304	Si-Di	S,125V,0,5A,<20ns	2c	Hit,Nec,++	BAV14..16
1S1305	Si-Di	S,125V,0,9A,<20ns	34a	Hit,Nec,++	-
1S131	Ref-Diode	8..9,5V,<0,01%/°C	?34a	Tos	-
1S131[Japan]	Ref-Di	8..9,5V,<0,01%/oC	?34a	Tos	-
1S131[Texas]	Si-Di	=1S130[Texas]:100V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1314	Si-Di	Modulator-Di	31a	Tos	-
1S1315	C-Di	AFC	31a	Nec	BA124..125,BB119,1S2790,1SV50,+
1S1316	Si-Di	Gl,Uni,40V,0,1A	31a	Nec	BA147/50,BA187..190,1N5606..09,+
1S1317	Si-Di	=1S1316:60V	31a	-	BA147/100,BA188..190,1N5606..09,+
1S1318	Si-Di	=1S1316:125V	31a	-	BA147/150,BA189..190,1N5606..09,+
1S1319	Si-Di	=1S1316:250V	31a	-	BA147/300,BA157..159,BAY21,+
1S132	Ref-Diode	8..9,5V,<0,005%/°C	?34a	Tos	-
1S132[Japan]	Ref-Di	8..9,5V,<0,005%/oC	?34a	Tos	-
1S132[Texas]	Si-Di	=1S130[Texas]:200V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1320	Si-Di	=1S1316:400V	31a	-	BA157..159,BAY89..90,BY207,+
1S1321	Si-Di	Gl-L,100V,5A(Tc=120o)	32a$	Nec	BYX38/300,BYX39/600
1S1322	Si-Di	=1S1321:200V	32a$	-	BYX38/300,BYX39/600
1S1323	Si-Di	=1S1321:300V	32a$	-	BYX38/300,BYX39/600
1S1324	Si-Di	=1S1321:400V	32a$	-	BYX38/600,BYX39/600
1S1325	Si-Di	=1S1321:500V	32a$	-	BYX38/600,BYX39/600
1S1326	Si-Di	=1S1321:600V	32a$	-	BYX38/600,BYX39/600

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1S1327	Si-Di	=1S1321:700V	32a$	-	BYX38/900,BYX39/800
1S1328	Si-Di	=1S1321:800V	32a$	-	BYX38/900,BYX39/800
1S1329	Si-Di	=1S1321:900V	32a$	-	BYX38/1200,BYX39/1000
1S133	Ref-Diode	8..9,5V,<0,002%/°C	?34a	Tos	-
1S133[Japan]	Ref-Di	8..9,5V,<0,002%/oC	?34a	Tos	-
1S1330	Si-Di	=1S1321:1000V	32a$	-	BYX38/1200,BYX39/1000
1S1331	Si-Di	GI-L,200V,500A(Tc=130o)	73a$	Nec	-
1S1332	Si-Di	=1S1331:400V	73a$	-	-
1S1333	Si-Di	=1S1331:600V	73a$	-	-
1S1334	Si-Di	=1S1331:800V	73a$	-	-
1S1335	Si-Di	=1S1331:1000V	73a$	-	-
1S1336	Si-Di	=1S1331:1200V	73a$	-	-
1S1337	Si-Di	=1S1331:1400V	73a$	-	-
1S1338	Si-Di	=1S1331:1600V	73a$	-	-
1S1339	Si-Di	=1S1331:1800V	73a$	-	-
1S134	Z-Di	3,8..5,4V,0,25W	31a	Tos	BZX55/C4V7,BZX79/C4V7,ZPD4,7,1N5230+
1S134[Japan]	Z-Di	3,8..5,4V,0,25W	31a	Tos	BZX55/C4V7,BZX79/C4V7,ZPD4,7,1N5230+
1S134[Texas]	Si-Di	=1S130[Texas]:400V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1340	Si-Di	=1S1331:2000V	73a$	-	-
1S1341	Si-Di	GI,Uni,50V,0,8A	34	Mit	BY126..127,BY133..134,1N4001..07,+
1S1342	Si-Di	=1S1341:100V	34	-	BY126..127,BY133..134,1N4002..07,+
1S1343	Si-Di	=1S1341:200V	34	-	BY126..127,BY133..134,1N4003..07,+
1S1344	Si-Di	=1S1341:300V	34	-	BY126..127,BY133..134,1N4004..07,+
1S1345	Si-Di	=1S1341:400V	34	-	BY126..127,BY133..134,1N4004..07,+
1S1346	Si-Di	=1S1341:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S1347	Si-Di	=1S1341:800V	34	-	BY127,BY133,BY227,1N4006..07,+
1S1348	Si-Di	=1S1341:1000V	34	-	BY127,BY133,BY227,1N4007,+
1S1349	Si-Di	=1S1341:1200V	34	-	BY127,BY133,BY227,GP10Q,+
1S135	Z-Di	=1S134[Japan]:5,2..6,2V	31a	Tos	BZX55/C5V6,BZX79/C5V6,ZPD5,6,1N5232..
1S135[Japan]	Z-Di	=1S134[Japan]:5,2..6,2V	31a	Tos	BZX55/C5V6,BZX79/C5V6,ZPD5,6,1N5232+
1S1350	Si-Di	GI,50V,2A	?32a$	Mit	(BY205/100,BY229/200,BYX49/300,++)
1S1351	Si-Di	=1S1350:100V	?32a$	-	(BY205/100,BY229/200,BYX49/300,++)
1S1352	Si-Di	=1S1350:200V	?32a$	-	(BY205/200,BY229/200,BYX49/300,++)
1S1353	Si-Di	=1S1350:300V	?32a$	-	(BY205/400,BY229/400,BYX49/300,++)
1S1354	Si-Di	=1S1350:400V	?32a$	-	(BY205/400,BY229/400,BYX49/600,++)
1S1355	Si-Di	=1S1350:600V	?32a$	-	(BY205/600,BY229/600,BYX49/600,++)
1S1356	Si-Di	=1S1350:800V	?32a$	-	(BY205/800,BY229/800,BYX49/900,++)
1S1357	Si-Di	=1S1350:1000V	?32a$	-	(BY205/1000,BY229/1000,BYX49/1200,++)
1S1358	Si-Di	=1S1350:1200V	?32a$	-	(BY329/1000,BY359/1300,BYX49/1200,++)
1S1359(A)	Si-Di	GI,Uni,200V,0,2A	31a	Stl	BY126..127,BY133..134,1N4003..07,+
1S136	Z-Di	6,0..7,1V,0,25W	31a	Tos	BZX55/C6V8,BZX79/C6V8,ZPD6,8,1N5235+
1S136[Japan]	Z-Di	=1S134[Japan]:6,0..7,1V	31a	Tos	BZX55/C6V8,BZX79/C6V8,ZPD6,8,1N5235+
1S136[Texas]	Si-Di	=1S130[Texas]:600V	31a	Tix	BA158..159,BY204/8,BY207,+
1S1360(A)	Si-Di	=1S1359:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1361(A)	Si-Di	=1S1359:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S1362(A)	Si-Di	=1S1359:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S1363(A)	Si-Di	=1S1359:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S1364(A)	Si-Di	=1S1359:1200V	31a	-	BY127,BY133,BY227,GP10Q,+
1S1365(A)	Si-Di	GI,Uni,200V,0,5A	31a	Stl	BY126..127,BY133..134,1N4003..07,+
1S1366(A)	Si-Di	=1S1365:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1367(A)	Si-Di	=1S1365:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S1368(A)	Si-Di	=1S1365:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S1369(A)	Si-Di	=1S1365:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S137	Z-Di	=1S134[Japan]:6,9..8,1V	31a	Tos	BZX55/C7V5,BZX79/C7V5,ZPD7,5,1N5236..
1S137[Japan]	Z-Di	=1S134[Japan]:6,9..8,1V	31a	Tos	BZX55/C7V5,BZX79/C7V5,ZPD7,5,1N5236+
1S1370(A)	Si-Di	=1S1365:1200V	31a	-	BY127,BY133,BY227,GP10Q,+
1S1371(A)	Z-Di	2..3,2V,0,25W	31a	Stl	BZX55/..,BZX79/..,ZPD..,1N5221..61,+
1S1372(A)	Z-Di	=1S1371:3..4V	31a	-	-
1S1373(A)	Z-Di	=1S1371:3,8..5V	31a	-	-
1S1374(A)	Z-Di	=1S1371:4,8..6V	31a	-	-
1S1375(A)	Z-Di	=1S1371:5,8..7V	31a	-	-
1S1376(A)	Z-Di	=1S1371:6..8V	31a	-	-
1S1377(A)	Z-Di	=1S1371:7,7..9,5V	31a	-	-
1S1378(A)	Z-Di	=1S1371:8,5..11V	31a	-	-

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1S1379(A)	Z-Di	=1S1371:10,5..14,5V	31a	-	-
1S138	Z-Di	=1S134[Japan]:7,9..9,1V	31a	Tos	BZX55/C8V2,BZX79/C8V2,ZPD8,2,1N5237+
1S138[Japan]	Z-Di	=1S134[Japan]:7,9..9,1V	31a	Tos	BZX55/C8V2,BZX79/C8V2,ZPD8,2,1N5237+
1S138[Texas]	Si-Di	=1S130[Texas]:800V	31a	Tix	BA159,BY204/8,BY208/800,+
1S1380(A)	Z-Di	=1S1371:14..18V	31a	-	-
1S1381(A)	Z-Di	=1S1371:17..23V	31a	-	-
1S1382(A)	Z-Di	=1S1371:22..28V	31a	-	-
1S1383(A)	Z-Di	=1S1371:27..33V	31a	-	-
1S1384(A)	Z-Di	=1S1371:32..38V	31a	-	-
1S1385(A)	Z-Di	=1S1371:37..48V	31a	-	-
1S1386(A)	Z-Di	2..3,2V,0,5W	31a	Stl	BZV85/..,BZX85/..,ZPY..,1N4728..58,+
1S1387(A)	Z-Di	=1S1386:3..4V	31a	-	-
1S1388(A)	Z-Di	=1S1386:3,8..5V	31a	-	-
1S1389(A)	Z-Di	=1S1386:4,8..6V	31a	-	-
1S139	Z-Di	=1S134[Japan]:8,9..10,1V	31a	Tos	BZX55/C9V1,BZX79/C9V1,ZPD9,1,1N5239..
1S139[Japan]	Z-Di	=1S134[Japan]:8,9..10,1V	31a	Tos	BZX55/C9V1,BZX79/C9V1,ZPD9,1,1N5239+
1S1390(A)	Z-Di	=1S1386:5,8..7V	31a	-	-
1S1391(A)	Z-Di	=1S1386:6,8..8V	31a	-	-
1S1392(A)	Z-Di	=1S1386:7,7..9,5V	31a	-	-
1S1393(A)	Z-Di	=1S1386:8,5..11V	31a	-	-
1S1394(A)	Z-Di	=1S1386:10,5..14,5V	31a	-	-
1S1395(A)	Z-Di	=1S1386:14..18V	31a	-	-
1S1396(A)	Z-Di	=1S1386:17..23V	31a	-	-
1S1397(A)	Z-Di	=1S1386:22..28V	31a	-	-
1S1398(A)	Z-Di	=1S1386:27..33V	31a	-	-
1S1399(A)	Z-Di	=1S1386:32..38V	31a	-	-
1S14	Ge-Di	Dem,45V,35mA	31a	Mat	AA113,1N34,1N54,1N60
1S140	Si-Di	-	31a	TI	BA157..159,BY204/4,BY206..207,+
1S140[Japan]	Z-Di	=1S134[Japan]:9,9..12,2V	31a	Tos	BZX55/C11,BZX79/C11,ZPD11,1N5241,+
1S140[Texas]	Si-Di	Gl,50V,0,3A	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1400(A)	Z-Di	=1S1386:37..48V	31a	-	-
1S1401(A)	Z-Di	=1S1386:47..58V	31a	-	-
1S1402	Z-Di	2..3,2V,1W	34a$	Stl	BZW22/..,BZX61/..,ZPY..,1N5913..38,+
1S1402R...1415R..	Z-Di	=1S1402..1415:	34b$	-	-
1S1402R..1415R...	Z-Di	=1S1402..1415:	34b$	-	-
1S1403	Z-Di	=1S1402:3..4V	34a$	-	-
1S1404	Z-Di	=1S1402:3,8..5V	34a$	-	-
1S1405	Z-Di	=1S1402:4,8..6V	34a$	-	-
1S1406	Z-Di	=1S1402:5,8..7V	34a$	-	-
1S1407	Z-Di	=1S1402:6,8..8V	34a$	-	-
1S1408	Z-Di	=1S1402:7,7..9,5V	34a$	-	-
1S1409	Z-Di	=1S1402:8,5..11V	34a$	-	-
1S141	Z-Di	=1S134[Japan]:11,8..13,9V	31a	Tos	BZX55/C13,BZX79/C13,ZPD13,1N5243,+
1S141[Japan]	Z-Di	=1S134[Japan]:11,8..13,9V	31a	Tos	BZX55/C13,BZX79/C13,ZPD13,1N5243,+
1S141[Texas]	Si-Di	=1S140[Texas]:100V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1410	Z-Di	=1S1402:10,5..14,5V	34a$	-	-
1S1411	Z-Di	=1S1402:14..18V	34a$	-	-
1S1412	Z-Di	=1S1402:17..23V	34a$	-	-
1S1413	Z-Di	=1S1402:22..28V	34a$	-	-
1S1414	Z-Di	=1S1402:27..33V	34a$	-	-
1S1415	Z-Di	=1S1402:32..38V	34a$	-	-
1S1417	Si-Di	Gl,contr.av.,800V,25A(Tc=135o)	32	Tos	1N4528..30
1S1418	Si-Di	=1S1417:1000V	32	-	1N4529..30
1S1419	Si-Di	=1S1417:1200V	32	-	1N4530
1S142	Z-Di	=1S134[Japan]:13,3..15,5V	31a	Tos	BZX55/C15,BZX79/C15,ZPD15,1N5245,+
1S142[Japan]	Z-Di	=1S134[Japan]:13,3..15,5V	31a	Tos	BZX55/C15,BZX79/C15,ZPD15,1N5245,+
1S142[Texas]	Si-Di	=1S140[Texas]:200V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1420(H)	Si-St	Level shift, <2,2V(2mA),0,1W	31a	Hit	-
1S1421(R)	Z-Di	=1S1402:37..48V	34a/b	-	-
1S1422(R)	Z-Di	=1S1402:47..58V	34a$/b&	-	-
1S1423	Z-Di	2..3,2V,3W	32a$	Stl	BZX98/..,BZY93/..,ZL..,1N2970..99,+
1S1423R...1438R..	Z-Di	=1S1423..1438:	32b&	-	-
1S1423R..1438R...	Z-Di	=1S1423..1438:	32b&	-	-
1S1424	Z-Di	=1S1423:3..4V	32a$	-	-

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1S1425	Z-Di	=1S1423:3,8..5V	32a$	-	-
1S1426	Z-Di	=1S1423:4,8..6V	32a$	-	-
1S1427	Z-Di	=1S1423:5,8..7V	32a$	-	-
1S1428	Z-Di	=1S1423:6,8..8V	32a$	-	-
1S1429	Z-Di	=1S1423:7,7..9,5V	32a$	-	-
1S143	Z-Di	=1S134(Japan):14,7..17,3V	31a	Tos	BZX55/C16,BZX79/C16,ZPD16,1N5246..
1S143(Japan)	Z-Di	=1S134(Japan):14,7..17,3V	31a	Tos	BZX55/C16,BZX79/C16,ZPD16,1N5246,+
1S1430	Z-Di	=1S1423:8,5..11V	32a$	-	-
1S1431	Z-Di	=1S1423:10,5..14,5V	32a$	-	-
1S1432	Z-Di	=1S1423:14..18V	32a$	-	-
1S1433	Z-Di	=1S1423:17..23V	32a$	-	-
1S1434	Z-Di	=1S1423:22..28V	32a$	-	-
1S1435	Z-Di	=1S1423:27..33V	32a$	-	-
1S1436	Z-Di	=1S1423:32..38V	32a$	-	-
1S1437	Z-Di	=1S1423:37..48V	32a$	-	-
1S1438	Z-Di	=1S1423:47..58V	32a$	-	-
1S1439	Z-Di	3,8..5V,10W	32a$	Stl	BZX98/..,BZY93/..,ZL..,1N2970..99,+
1S1439R..1452R..	Z-Di	=1S1439..1452:	32b&	-	-
1S1439R..1452R...	Z-Di	=1S1439..1452:	32b&	-	-
1S144	Si-Di	-	31a	Toshiba	-
1S144(Japan)	Si-Di	Meawerkschutz/meterprotection,65mA	31a	Tos	-
1S144(Texas)	Si-Di	=1S140(Texas):400V	31a	Tix	BA157..159,BY204/4,BY206..207,+
1S1440	Z-Di	=1S1439:4,8..6V	32a$	-	-
1S1441	Z-Di	=1S1439:5,8..7V	32a$	-	-
1S1442	Z-Di	=1S1439:6,8..8V	32a$	-	-
1S1443	Z-Di	=1S1439:7,7..9,5V	32a$	-	-
1S1444	Z-Di	=1S1439:8,5..11V	32a$	-	-
1S1445	Z-Di	=1S1439:10,5..14,5V	32a$	-	-
1S1446	Z-Di	=1S1439:14..18V	32a$	-	-
1S1447	Z-Di	=1S1439:17..23V	32a$	-	-
1S1448	Z-Di	=1S1439:22..28V	32a$	-	-
1S1449	Z-Di	=1S1439:27..33V	32a$	-	-
1S145	C-Diode	FM/VHF-AFC,20V,8..12pF(10mA)	31a	Tos	BA124..125,BB119,1S2790,1SV50..
1S145(Japan)	C-Di	FM/VHF-AFC,20V,8..12pF(10mA)	31a	Tos	BA124..125,BB119,1S2790,1SV50,+
1S1450	Z-Di	=1S1439:32..38V	32a$	-	-
1S1451	Z-Di	=1S1439:37..48V	32a$	-	-
1S1452	Z-Di	=1S1439:47..58V	32a$	-	-
1S1454	Si-Di	Gl-L,400V,6A(Tc=120o)	73b&	Fjd	BYX42/600,BYX98/600
1S1455	Si-Di	=1S1454:800V	73b&	-	BYX42/900,BYX98/900
1S1456	Si-Di	=1S1454:1000V	73b&	-	BYX42/1200,BYX98/1200
1S1457	Si-Di	=1S1454:1200V	73b&	-	BYX42/1200,BYX98/1200
1S1458	Si-Di	SS,60V,0,1A,<2ns	31a	-	BAW62,BAX95,1N4148..49,1N4151,+
1S1459	Si-Di	SS,60V,0,15A,<2ns	31a	-	BAW62,BAX95,1N4148..49,1N4151,+
1S146	Si-Di	-	31a	Fuji	BY126..127,BY133..135,1N4002..07..
1S146(Japan)	Si-Di	Gl,Uni,100V,0,6A	31a	Fui	BY126..127,BY133..135,1N4002..07,+
1S1460	Si-Di	SS,60V,0,35A,<2ns	31a	-	BAW76
1S1461	Si-Di	Gl-L,contr.av.,800V,12A(Tc=135o)	32b&	Tos	BYX25/800R
1S1462	Si-Di	=1S1461:1000V	32b&	-	BYX25/1000R
1S1463	Si-Di	=1S1461:1200V	32b&	-	BYX25/1200R
1S1464	Si-Di	UHF-M,800MHz	31a	Say	-
1S1465	Ge-Di	TV-Damper-Di,250V,10A(ss)	22	Tos	-
1S1466	Si-Di	SS,60V,0,08A,<2ns	31a	-	BAW62,BAX95,1N4148..49,1N4151,+
1S1467	Si-Di	SS,60V,0,25A,<2ns	31a	-	BAW62,BAX95,1N4148..49,1N4151,+
1S147	Si-Di	-	31a	-	BY126..127,BY133..134,1N4003..07..
1S147(Japan)	Si-Di	=1S146(Japan):200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S1471	Si-Di	Gl,contr.av.,1000V,1A	34a$	Nec	BYV36E,BYV96E,BYW56,1N4249
1S1472	Si-Di	Gl,Uni,600V,0,15A	2b	Tos	BA158..159,BAY89..90,BY207,+
1S1473(H,K)	Si-Di	SS,30V,0,1A,<4ns	12c	Hit	BA318,BAY38,1N4148..49,1N4151,+
1S1474	Si-Di	Gl,contr.av.,200V,1,5A	34	Shi	BYV36A,BYV95A,BYW52..56,BYW95A
1S1475	Si-Di	=1S1474:400V	34	-	BYV36B,BYV95B,BYW53..56,BYW95B
1S1476	Si-Di	=1S1474:600V	34	-	BYV36C,BYV95C,BYW54..56,BYW95C
1S1477	Si-Di	=1S1474:800V	34	-	BYV36D,BYV96D,BYW55..56,BYW96D
1S1478	Si-Di	=1S1474:1000V	34	-	BYV36E,BYV96E,BYW56,BYW96E
1S1479	Si-Di	=1S1474:1200V	34	-	SSiB9880A

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1S148	Si-Di	-	31a	-	BY126..127,BY133..134,1N4004..07..
1S148[Japan]	Si-Di	=1S146[Japan]:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1480	Si-Di	Gl-L,200V,20A(Tc=90o)	73a$	Shi	1N4525..30
1S1481	Si-Di	=1S1480:400V	73a$	-	1N4526..30
1S1482	Si-Di	=1S1480:600V	73a$	-	1N4527..30
1S1483	Si-Di	=1S1480:800V	73a$	-	1N4528..30
1S1484	Si-Di	=1S1480:1000V	73a$	-	1N4529..30
1S1485	Si-Di	=1S1480:1200V	73a$	-	1N4530
1S1486	Si-Di	Gl,contr.av.,100V,0,4A	31a	Shi	BYV36A,BYV95A,BYW52..56,BYW95A
1S1487	Si-Di	=1S1486:200V	31a	-	BYV36A,BYV95A,BYW52..56,BYW95A
1S1488	Si-Di	Gl,Uni,200V,1,5A	34	Hit	BY226..227,BY251..255,1N5393..99,+
1S1489	Si-Di	=1S1488:400V	34	-	BY226..227,BY252..255,1N5395..99,+
1S149	Si-Di	-	31a	-	BY126..127,BY133..134,1N4004..07..
1S149[Japan]	Si-Di	=1S146[Japan]:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1490	Si-Di	=1S1488:600V	34	-	BY226..227,BY253..255,1N5397..99,+
1S1491	Si-Di	=1S1488:800V	34	-	BY227,BY254..255,1N5398..99,+
1S1492	Si-Di	=1S1488:1000V	34	-	BY227,BY255,BYW56,1N5399,+
1S1493	Si-Di	Gl-L,200V,30A	32a$	Hit	BYX56/600,BYX97/300,
1S1493R..1495R..	Si-Di	=1S1493..1495:	32b&	-	BYX56/..R,BYX97/..R
1S1493R..1495R...	Si-Di	-	32b&	-	BYX56/..R,BYX97/..R
1S1494	Si-Di	=1S1493:400V	32a$	-	BYX56/600,BYX97/600,
1S1495	Si-Di	=1S1493:600V	32a$	-	BYX56/600,BYX97/600,
1S1496	Si-Di	Gl-L,200V,50A(Tc=70o)	73a$	Hit	1N3289..97
1S1496R...1498R..	Si-Di	=1S1496..1498:	73b&	-	1N3289R..97R
1S1496R..1498R...	Si-Di	-	73b&	-	1N3289R..97R
1S1497	Si-Di	=1S1496:400V	73a$	-	1N3291..97
1S1498	Si-Di	=1S1496:600V	73a$	-	1N3293..97
1S15	Ge-Di	Dem,45V,35mA	31a	Mat	AA113,1N34,1N54,1N60
1S150	Si-Di	-	31a	-	BY126..127,BY133..134,1N4005..07..
1S150[Japan]	Si-Di	=1S146[Japan]:500V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S1500	C-Di	AFC	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S1501	C-Di	AFC	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S1502	C-Di	AFC	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S1503	C-Di	AFC	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S151	Si-Di	Gl-L,100V,1,5A	32a$	Nec	BYX38/300,BYX39/600
1S1514(M)	Si-Di	SS,90V,0,12A,<2ns	31a	Tos	BA219,1N4148..49,1N4446..49,+
1S1515(M)	Si-Di	SS,55V,0,12A,<2ns	31a	Tos	BA219,1N4148..49,1N4446..49,+
1S1516(M)	Si-Di	SS,55V,0,12A,<2ns	31a	Tos	BA219,1N4148..49,1N4446..49,+
1S1517(A)	Si-Di	TV-Damper-Di,1500V,0,5A	34a$	Tos	BY228,BY269,BY400,BY448
1S1518	Si-Di	Gl-L,200V,10A	75a$	Sak	1N3493..95
1S1518R...1522R..	Si-Di	=1S1518..1522:	75b&	-	1N3493R..95R
1S1518R..1522R...	Si-Di	-	75b&	-	1N3493R..95R
1S1519	Si-Di	=1S1518:400V	75a$	-	1N3495
1S152	Si-Di	=1S151:200V	32a$	-	BYX38/300,BYX39/600
1S1520	Si-Di	=1S1518:500V	75a$	-	-
1S1521	Si-Di	=1S1518:600V	75a$	-	-
1S1522	Si-Di	=1S1518:800V	75a$	-	-
1S1523(R)	Si-Di	Gl-Array,200V,80A(Tc=75o)	-	Sak	-
1S1524(R)	Si-Di	=1S1523:500V	-		-
1S1525(R)	Si-Di	=1S1523:800V	-		-
1S1526	Si-Br	Gl,100V,0,6A	-	Sak	B100C600,etc.
1S1527	Si-Br	=1S1526:200V	-		B200C600,etc.
1S1528	Si-Br	=1S1526:400V	-		B400C600,etc.
1S1529	Si-Br	=1S1526:600V	-		B600C600,etc.
1S153	Si-Di	=1S151:300V	32a$	-	BYX38/300,BYX39/600
1S1530	Si-Br	=1S1526:800V	-		B800C600,etc.
1S1531	Si-Br	=1S1526:1000V	-		B1000C600,etc.
1S1532	Si-Di	SS,35V,0,06A,<4ns	31a	Sak	BA218,BAX13,BAX91,1N4148..49,+
1S154	Si-Di	=1S151:400V	32a$	-	BYX38/600,BYX39/600
1S1540(N)	Z-Di	68..83V,35W(Tc=55o)	23	Tos	-
1S1541(N)	Z-Di	=1S1540:77..103V	23	-	-
1S1542(N)	Z-Di	=1S1540:103..115V	23	-	-
1S1543(N)	Z-Di	=1S1540:140..168V	23	-	-
1S1544(A)	Si-Di	S,30V,0,1A,<100ns	31a	Nec	BAV17..21,BAX90,BAX94,BAY41..43+

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1S1545	Si-Di	S,30V,0,1A,<100ns	31a	Nec	BAV17..21,BAX90,BAX94,BAY41..43+
1S1546	Si-Di	GI,Uni,100V,0,6A	31a	Tos	BY126..127,BY133..135,1N4002..07,+
1S1547	Si-Di	=1S1546:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S1548	Si-Di	=1S1546:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1549	Si-Di	UHF-M,890MHz	31a	Tos	-
1S155	Si-Di	=1S151:500V	32a$	-	BYX38/600,BYX39/600
1S1550	Z-Di	=1S1540:162..195V	23	-	-
1S1551	Si-Di	Varaktor,HF-Multipl	32a$	Tos	-
1S1552	Si-Di	Varaktor,HF-Multipl	32a$	Tos	-
1S1553	Si-Di	Dem,Uni,70V,0,1A	31a	Tos	BA147/100,BA188..190,1N5606..09,+
1S1554	Si-Di	=1S1553:55V	31a	-	BA147/100,BA188..190,1N5606..09,+
1S1555	Si-Di	=1S1553:35V	31a	-	BA147/50,BA187..190,1N5606..09,+
1S1556	Si-Di	Varaktor,HF-Multipl	32a$	Tos	-
1S1557	Si-Di	Varaktor,HF-Multipl	32a$	Tos	-
1S1558	Si-Di	Varaktor,HF-Multipl	32a$	Tos	-
1S156	Si-Di	=1S151:600V	32a$	-	BYX38/600,BYX39/600
1S1560(R)	Si-Di	GI,100V,3A(Tc=120o)	-	Tos	(BY205/200,BY229/200,BYX49/300,++)
1S1561	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1562	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1563	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1564	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1565	Si-Di	GI-L,800V,350A(Tc=90o)	?73	Tos	-
1S1566	Si-Di	=1S1565:1000V	?73	-	-
1S1567	Si-Di	=1S1565:1200V	?73	-	-
1S1568	Si-Di	=1S1565:1500V	?73	-	-
1S1569	Si-Di	=1S1565:1800V	?73	-	-
1S157	Si-Di	GI-L,100V,1A	32a$	Nec	BYX38/300,BYX39/600
1S1570	Si-Di	=1S1565:2000V	?73	-	-
1S1571	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1572	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1573	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1574	Si-Di	Varaktor,HF-Multipl	Koax	Tos	-
1S1575	Si-Di	GI-L,400V,12A(Tc=120o)	32	Tos	1N4526..30
1S1576	Si-Di	=1S1575:600V	32	-	1N4527..30
1S1577	Si-Di	=1S1575:800V	32	-	1N4528..30
1S1578	Si-Di	=1S1575:1000V	32	-	1N4529..30
1S1579	C-Di	Dual,TV-AFC(Horiz.-0),60V,0,05A	7p	Tos	-
1S158	Si-Di	=1S157:200V	32a$	-	BYX38/300,BYX39/600
1S1580	C-Di	=1S1579:35V	7p	-	-
1S1581	Si-Di	Varaktor,10GHz	Koax	Tos	-
1S1582	C-Di	AFC	31a	Tos	BA124..125,BB119,1S2790,1SV50,+
1S1583	Si-Di	Varaktor	32	Tos	-
1S1585	Si-Di	SS,90V,0,15A,<2ns	31a	Tos	BAW62,BAX95,1N4148..49,1N4151,+
1S1586	Si-Di	SS,55V,0,15A,<2ns	31a	Tos	BAW62,BAX95,1N4148..49,1N4151,+
1S1587	Si-Di	SS,55V,0,13A,<2ns	31a	Tos	BAW62,BAX95,1N4148..49,1N4151,+
1S1588	Si-Di	SS,35V,0,12A,<4ns	31a	Tos	BAW62,BAX95,1N4148..49,1N4151,+
1S1589	Si-Di	SS,40V,0,06A,<4ns	31a	Sak	BA218,BAX13,BAY71,1N4148..49,+
1S159	Si-Di	=1S157:300V	32a$	-	BYX38/300,BYX39/600
1S1591	Si-Di	GI,S,600V,0,03A,<300ns	31a	SAk	BA158..159,BY203/12,SHG1,+
1S1592	Si-Di	=1S1591:800V	31a	-	BA159,BY203/12,BY268..269,SHG1,+
1S1593	Si-Di	=1S1591:1000V	31a	-	BA159,BY203/12,BY268..269,SHG1,+
1S1594	Si-Di	=1S1591:1200V	31a	-	BY203/12,BY268..269,SHG1,5,+
1S1595	Si-Di	=1S1591:1500V	31a	-	BY203/16,BY269,SHG1,5
1S1596	Si-Di	=1S1591:1800V	31a	-	BY203/20,SHG2
1S1597	Si-Di	GI,Uni,35V,0,1A	31a	Mit	BA147/50,BA187..190,1N5606..09,+
1S1598	Si-Di	=1S1597:50V	31a	-	BA147/50,BA187..190,1N5606..09,+
1S1599	Si-Di	=1S1597:100V	31a	-	BA147/100,BA188..190,1N5606..07,+
1S16	Ge-Di	Dem,45V,35mA	31a	Mat	AA113,1N34,1N54,1N60
1S160	Si-Di	GI-L,50V,10A(Tc=120o)	32a$	Nec	BYX42/300,BYX98/300
1S1600	Si-Di	=1S1597:200V	31a	-	BA147/230,BA190,BAY21,BAY88..90+
1S1601	Si-Di	=1S1597:300V	31a	-	BA147/300,BAY21,BAY88..90,+
1S1602	Si-Di	=1S1597:400V	31a	-	BA157..159,BAY89..90,BY207,+
1S1604	Si-Di	GI,Uni,100V,1,1A	31a	Hit	BY126..127,BY133..135,1N4002..07,+
1S1605	Si-Di	GI,Uni,800V,0,5A	31a	Hit	BY127,BY133,BY227,1N4006..07,+

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1S1606	Si-Di	Gl-L,200V,20A(Tc=100o)	32a$	Hit	1N4525..30
1S1606R...1607R..	Si-Di	=1S1606..1607:	32b&	-	D24/400C
1S1606R..1607R...	Si-Di	-	32b&	-	D24/400C
1S1607	Si-Di	=1S1606:300V	32a$	-	1N4526..30
1S1608	Si-Di	Gl,Uni,1000V,0,5A	31a	Hit	BY127,BY133,BY227,1N4007,+
1S1609	Si-Di	=1S1608:1300V	31a	-	BY127,BY133,BY227,GP10V,+
1S161	Si-Di	=1S160:100V	32a$	-	BYX42/300,BYX98/300
1S1610	Si-Di	=1S1608:1500V	31a	-	BY269,DM513,EM516,GP10W
1S1611	Si-Di	kV-Gl,6kV,0,06A	31a	Isi	1N5183
1S1612	Si-Di	=1S1611:12kV	31a	-	1N3052
1S1613	Si-Di	=1S1611:18kV	31a	-	1N3055
1S1614	Si-Di	Gl-L,800V,50A(Tc=135o)	73b&	Tos	1N3294R..97R
1S1615	Si-Di	=1S1614:1000V	73b&	-	1N3295R..97R
1S1616	Si-Di	=1S1614:1200V	73b&	-	1N3296R..97R
1S1617	C-Di	FM/VHF-AFC	31a	Nec	BA111,BA124,1S2790,1SV50,+
1S1618	C-Di	FM/VHF-AFC	31a	Nec	BA111,BA124,1S2790,1SV50,+
1S1619	C-Di	FM/VHF-AFC	31a	Nec	BA111,BA124,1S2790,1SV50,+
1S162	Si-Di	=1S160:200V	32a$	-	BYX42/300,BYX98/300
1S1620	Si-Di	SS,50V,0,115A,<4ns	31a	Mat	BAW62,BAX95,1N4148..49,1N4151,+
1S1621	Si-Di	S,175V,0,1A,<400ns	31a	Tos	BA195,BAX15,BAX17,1N3070,+
1S1622	Si-Di	Gl,Uni,100V,0,3A	31a	Tos	BA157..159,BY204/4,BY206..207,+
1S1623	Si-Di	=1S1622:200V	31a	-	BA157..159,BY204/4,BY206..207,+
1S1624	Si-Di	=1S1622:400V	31a	-	BA157..159,BY204/4,BY207,+
1S1625	Si-Di	=1S1622:600V	31a	-	BA158..159,BY204/8,BY207,+
1S1626	Si-Di	Gl-L,contr.av.,800V,6A(Tc=135o)	32	Tos	1N4509..11
1S1627	Si-Di	=1S1626:1000V	32	-	1N4510..11
1S1628	Si-Di	=1S1626:1200V	32	-	1N4511
1S1629	Si-Di	Gl-L,contr.av.,800V,3A(Tc=135o)	32	Tos	BYX39/800
1S163	Si-Di	=1S160:300V	32a$	-	BYX42/300,BYX98/300
1S1630	Si-Di	=1S1629:1000V	32	-	BYX39/1000
1S1631	Si-Di	=1S1629:1200V	32	-	BYX39/1200
1S1632	Si-Di	Gl-L,150V,150A(Tc=110o)	73	Tos	1N4588..4596
1S1633	Si-Di	=1S1632:300V	73	-	1N4589..4596
1S1634	Si-Di	=1S1632:400V	73	-	1N4590..4596
1S1635	Si-Di	=1S1632:500V	73	-	1N4591..4596
1S1636	Si-Di	=1S1632:600V	73	-	1N4592..4596
1S1637	Si-Di	=1S1632:700V	73	-	1N4593..4596
1S1638	Si-Di	=1S1632:800V	73	-	1N4593..4596
1S1639	Si-Di	=1S1632:1000V	73	-	1N4594..4596
1S164	Si-Di	=1S160:400V	32a$	-	BYX42/600,BYX98/600
1S1640(R)	Si-Di	Gl-L,100V,15A(Tc=120o)	-	Tos	(BYX25/600,BYX99/300)
1S1641(R)	Si-Di	Gl-L,100V,20A(Tc=120o)	-	Tos	(BYX25/600)
1S1642	Si-Di	Gl-L,400V,25A(Tc=90o)	32a	-	1N4526..30
1S1642R	Si-Di	=1S1642:	32b	Tos	D24/400C
1S1643	Si-Di	Gl-L,150V,50A(Tc=120o)	73a$	Tos	1N3289..97
1S1643R...1644R..	Si-Di	=1S1643..1644:	73b&	-	1N3289R..97R
1S1643R..1644R...	Si-Di	-	73b&	-	1N3289R..97R
1S1644	Si-Di	=1S1643:300V	73a$	-	1N3290..97
1S1645	Si-Di	Gl-L,150V,100A(Tc=110o)	73a$	Tos	1N3289..97
1S1645R...1646R..	Si-Di	=1S1645..1646:	73b&	-	1N3289R..97R
1S1645R..1646R...	Si-Di	-	73b&	-	1N3289R..97R
1S1646	Si-Di	=1S1645:300V	73a$	-	1N3290..97
1S1647	Si-Di	Gl-L,150V,200A(Tc=100o)	73a$	Tos	1N3736..44
1S1647R...1648R..	Si-Di	=1S1647..1648:	73b&	-	1N3736R..44R
1S1647R..1648R...	Si-Di	-	73b&	-	1N3736R..44R
1S1648	Si-Di	=1S1647:300V	73a$	-	1N3737..44
1S165	Si-Di	=1S160:500V	32a$	-	BYX42/600,BYX98/600
1S1650	C-Di	AFC	31a	Tos	BA124..125,BB119,1S2790,1SV50,+
1S1651	C-Di	AFC	31a	-	BA124..125,BB119,1S2790,1SV50,+
1S1652	Si-Di	Gl-L,150V,12A(Tc=50o)	32a$	Tos	1N4525..30
1S1652R...1653R..	Si-Di	=1S1652..1653:	32b&	-	D24/400C
1S1652R..1653R...	Si-Di	-	32b&	-	D24/400C
1S1653	Si-Di	=1S1652:300V	32a$	-	1N4526..30
1S1654	Si-Di	Gl-L,150V,25A(Tc=50o)	32a$	Tos	1N4525..30

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1S1654R...1655R..	Si-Di	=1S1654..1655:	32b&	-	D24/400C
1S1654R..1655R...	Si-Di	-	32b&	-	D24/400C
1S1655	Si-Di	=1S1654:300V	32a$	-	1N4526..30
1S1656	Ge-Di	TV-Damper-Di,150V,6A(Tc=50o)	22	Mit	-
1S1657	Ge-Di	=1S1656:200V	22	-	-
1S1658	C-Di	FM-AFC	31a	Tos	BA111,BA124,1S2790,1SV50,+
1S1659	Si-Di	SS,10V,0,05A,<1ns	31a	Nec	BAY82,1N4244,1N4376
1S166	Si-Di	=1S160:600V	32a$	-	BYX42/600,BYX98/600
1S1660	Si-Di	GI-L,150V,3A	32a$	Tos	BYX38/300,BYX39/900
1S1660R...1661R..	Si-Di	=1S1660..1661:	32b&	-	BYX38/300R,BYX39/900R
1S1660R..1661R...	Si-Di	-	32b&	-	BYX38/300R,BYX39/900R
1S1661	Si-Di	=1S1660:300V	32a$	-	BYX38/300,BYX39/900
1S1662	Si-Di	GI-L,150V,6A	32a$	Tos	BYX38/300,BYX39/900
1S1662R...1663R..	Si-Di	=1S1662..1663:	32b&	-	BYX38/300R,BYX39/900R
1S1662R..1663R...	Si-Di	-	32b&	-	BYX38/300R,BYX39/900R
1S1663	Si-Di	=1S1662:300V	32a$	-	BYX38/300,BYX39/900
1S1664	Si-Di	GI,Uni,100V,1A	31a	Inr	BY126..127,BY133..135,1N4002..07,+
1S1665	Si-Di	=1S1664:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S1666	Si-Di	=1S1664:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1667	Si-Di	=1S1664:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S1668	Si-Di	=1S1664:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S1669	Si-Di	=1S1664:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S167	Si-Di	GI-L,100V,5A(Tc=120o)	32a$	Nec	BYX38/300,BYX39/600
1S1670	Si-Br	GI,100V,1,8A	42	Inr	B100C2000,etc
1S1671	Si-Br	=1S1670:200V	42	-	B200C2000,etc
1S1672	Si-Br	=1S1670:400V	42	-	B400C2000,etc
1S1673	Si-Br	=1S1670:600V	42	-	B600C2000,etc
1S1674	Si-Br	=1S1670:800V	42	-	B800C2000,etc
1S1675	Si-Br	=1S1670:1000V	42	-	B1000C2000,etc
1S1676	Ge-Di	Tunnel-Di	Koax	Nec	-
1S1677	Ge-Di	Tunnel-Di	Koax	Nec	-
1S1678	Si-Di	GI,Uni,100V,1,3A	34	Inr	BY251..255,BY226..227,1N5392..99,+
1S1679	Si-Di	=1S1678:200V	34	-	BY251..255,BY226..227,1N5393..99,+
1S168	Si-Di	=1S167:200V	32a$	-	BYX38/300,BYX39/600
1S1680	Si-Di	=1S1678:400V	34	-	BY252..255,BY226..227,1N5395..99,+
1S1681	Si-Di	=1S1678:600V	34	-	BY253..255,BY226..227,1N5397..99,+
1S1682	Si-Di	=1S1678:800V	34	-	BY254..255,BY227,1N5398..99,+
1S1683	Si-Di	=1S1678:1000V	34	-	BY255,BY227,BYW56,1N5399,+
1S1684	Si-Di	=1S1678	34a	-	→1S1678
1S1685	Si-Di	=1S1679	34a	-	→1S1679
1S1686	Si-Di	=1S1680	34a	-	→1S1680
1S1687	Si-Di	=1S1681	34a	-	→1S1681
1S1688	Si-Di	=1S1682	34a	-	→1S1682
1S1689	Si-Di	=1S1683	34a	-	→1S1683
1S169	Si-Di	=1S167:300V	32a$	-	BYX38/300,BYX39/600
1S1690(A)	Si-Di	GI,Uni,30V,0,09A	31a	Njr	BA147/50,BA187..190,1N5606..09,+
1S1691(A)	Si-Di	GI,Uni,36V,0,1A	31a	Njr	BA147/50,BA187..190,1N5606..09,+
1S1692(A)	Si-Di	GI,Uni,70V,0,075A	31a	Njr	BA147/100,BA188..190,1N5606..09,+
1S1693(A)	Si-Di	GI,Uni,70V,0,1A	31a	Njr	BA147/100,BA188..190,1N5606..09,+
1S1694(A)	Si-Di	GI,Uni,130V,0,1A	31a	Njr	BA147/150,BA189..190,1N5606..07,+
1S1695(A)	Si-Di	GI,Uni,200V,0,04A	31a	Njr	BA147/230,BA190,BAY21,BAY88..90+
1S1696(A)	Si-Di	GI,Uni,225V,0,1A	31a	Njr	BA147/230,BAY21,BAY88..90,+
1S1697(A)	Si-Di	GI,Uni,300V,0,1A	31a	Njr	BA147/300,BAY21,BAY88..90,+
1S1698(A)	Si-Di	GI,Uni,380V,0,1A	31a	Njr	BA158..159,BA199/450,BAY89..90,+
1S1699	Si-Di	GI,S,30V,0,02A,<250ns	31a	Njr	BA157..159,BAV17..21,BAW48..50,+
1S17	Ge-Di	Uni,115V,50mA	31a	Mat	AA117..118,AA132..133
1S170	Si-Di	GI-L,50V,20A(Tc=120o)	32a$	Nec	1N4525..30
1S1700	Si-Di	=1S1699:40V,0,12A	31a	Njr	BA157..159,BAV17..21,BAW48..50,+
1S1701	Si-Di	=1S1699:60V,0,1A	31a	Njr	BA157..159,BAV18..21,BAW49..50,+
1S1702	Si-Di	=1S1699:65V,0,12A	31a	Njr	BA157..159,BAV19..21,BAW49..50,+
1S1703	Si-Di	=1S1699:100V,0,02A	31a	Njr	BA157..159,BAV19..21,BAW49..50,+
1S1704(A)	Si-Di	=1S1699:100V,0,04A	31a	Njr	BA157..159,BAV19..21,BAW49..50,+
1S1705(A)	Si-Di	=1S1699:120V,0,2A	31a	Njr	BA157..159,BAV19..21,BAW50,+
1S1706	Si-Di	=1S1699:200V,0,02A	31a	Njr	BA157..159,BAV20..21,BAW50,+

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1S1707(A)	Si-Di	=1S1699:200V,0,04A	31a	Njr	BA157..159,BAV20..21,BAW50,+
1S1708	Si-Di	=1S1699:200V,0,1A	31a	Njr	BA157..159,BAV20..21,BAW50,+
1S1709	Si-Di	=1S1699:220V,0,1A	31a	Njr	BA157..159,BA198,BAV21,+
1S171	Si-Di	=1S170:100V	32a$	-	1N4525..30
1S1710	Si-Di	SS,30V,0,05A,<4ns	31a	Njr	BA218,BAX13,BAX91,1N4148..49,+
1S1711	Si-Di	SS,40V,0,05A,<4ns	31a	Njr	BA218,BAX13,BAX91,1N4148..49,+
1S1712(A)	Si-Di	SS,100V,0,075A,<4ns	31a	Njr	BA219,BAX96,1N4148..49,1N4151,+
1S1713	Si-Di	SS,50V,0,075A,<2ns	31a	Njr	BAW62,BAX95,1N4148..49,1N4151,+
1S1714	Si-Di	SS,75V,0,075A,<2ns	31a	Njr	BAW62,BAX95,1N4148..49,1N4151,+
1S1715	Z-Di	6..7,1V,0,3W	7c	Tos	BZX55/..,BZX79/..,ZPD..,1N5234..40,+
1S1716	Z-Di	=1S1715:6,9..8,1V	7c	-	-
1S1717	Z-Di	=1S1715:7,9..9,1V	7c	-	-
1S1718	Z-Di	=1S1715:8,9..10,1V	7c	-	-
1S1719	Diac	Ub=28..42V,Ib<0,2mA,Itsm=2A	31l	Tos	1N5762,N413N,D3202U
1S172	Si-Di	=1S170:200V	32a$	-	1N4525..30
1S1720(R)	Si-Di	Gl-L,250V,10A(Tc=120o)	-	Tos	(BY239/400,BYX72/300)
1S1721	Si-Di	UHF,S-Band-M	Koax	Tos	-
1S1722	Si-Di	UHF,S-Band-M	31a	Tos	-
1S1723	Si-Di	Gl,Uni,100V,1,3A	34a$	-	BY251..255,BY226..227,2N5392..99,+
1S1723R...1733R..	Si-Di	=1S1723..1733:	34b&	-	→1S1723..1733
1S1723R..1733R...	Si-Di	-	34b&	-	-
1S1724	Si-Di	=1S1723:150V	34a$	-	BY251..255,BY226..227,2N5393..99,+
1S1725	Si-Di	=1S1723:200V	34a$	-	BY251..255,BY226..227,2N5393..99,+
1S1726	Si-Di	=1S1723:250V	34a$	-	BY252..255,BY226..227,2N5394..99,+
1S1727	Si-Di	=1S1723:300V	34a$	-	BY252..255,BY226..227,2N5394..99,+
1S1728	Si-Di	=1S1723:400V	34a$	-	BY252..255,BY226..227,2N5395..99,+
1S1729	Si-Di	=1S1723:500V	34a$	-	BY253..255,BY226..227,2N5396..99,+
1S173	Si-Di	=1S170:300V	32a$	-	1N4526..30
1S1730	Si-Di	=1S1723:600V	34a$	-	BY253..255,BY226..227,2N5397..99,+
1S1731	Si-Di	=1S1723:800V	34a$	-	BY254..255,BY227,2N5398..99,+
1S1732	Si-Di	=1S1723:1000V	34a$	-	BY255,BY227,BYX86..87,2N5399,+
1S1733	Si-Di	=1S1723:1200V	34a$	-	BY255,BY227,BYW17/1200,BYX87,+
1S1734	Z-Di	4,5..5,5V,1W	34	-	BZW22/..,BZX61/..,ZPY..,1N5917..53,+
1S1735	Z-Di	=1S1734:5..6,5V	34	-	-
1S1736	Z-Di	=1S1734:6..8V	34	-	-
1S1737	Z-Di	=1S1734:7..10V	34	-	-
1S1738	Z-Di	=1S1734:9..12V	34	-	-
1S1739	Z-Di	=1S1734:11..14V	34	-	-
1S174	Si-Di	=1S170:400V	32a$	-	1N4526..30
1S1740	Z-Di	=1S1734:13..16V	34	-	-
1S1741	Z-Di	=1S1734:15..19V	34	-	-
1S1742	Z-Di	=1S1734:18..22V	34	-	-
1S1743	Z-Di	=1S1734:20..27V	34	-	-
1S1744	Z-Di	=1S1734:25..35V	34	-	-
1S1745	Z-Di	=1S1734:30..40V	34	-	-
1S1746	Z-Di	=1S1734:35..50V	34	-	-
1S1747	Z-Di	=1S1734:45..60V	34	-	-
1S1748	Z-Di	=1S1734:55..70V	34	-	-
1S1749	Z-Di	=1S1734:65..80V	34	-	-
1S175	Si-Di	=1S170:500V	32a$	-	1N4527..30
1S1750	Z-Di	=1S1734:75..90V	34	-	-
1S1751	Z-Di	=1S1734:85..100V	34	-	-
1S1752	Z-Di	=1S1734:95..110V	34	-	-
1S1753	Z-Di	=1S1734:100..120V	34	-	-
1S1754	Z-Di	=1S1734:110..130V	34	-	-
1S1755	Z-Di	=1S1734:120..140V	34	-	-
1S1756	Z-Di	=1S1734:130..150V	34	-	-
1S1757	Si-Di	Modulator	31a	Tos	-
1S1758	Si-Di	Modulator	31a	Tos	-
1S1759	Si-Di	Modulator	31a	Tos	-
1S176	Si-Di	=1S170:600V	32a$	-	1N4527..30
1S1760	Ge-Di	Tunnel-Di	34	Nec	-
1S1761	Ge-Di	Tunnel-Di	34	Nec	-
1S1762	Ge-Di	Tunnel-Di	34	Nec	-

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1S1763	Ge-Di	Tunnel-Di	34	Nec	-
1S1764	Ge-Di	Tunnel-Di	34	Nec	-
1S1765	C-Di	FM/VHF-AFC	31a	Nec	BA111,BA124,1S2790,1SV50,+
1S1766	Z-Di	4,5..5,5V,0,25W	31a	-	BZX55/..,BZX79/..,ZPY..,1N5230..59,+
1S1767	Z-Di	=1S1766:5..6,5V	31a	-	-
1S1768	Z-Di	=1S1766:6..8V	31a	-	-
1S1769	Z-Di	=1S1766:7..10V	31a	-	-
1S177	Si-Di	Gl-L,100V,15A(Tc=120o)	32a$	Nec	1N4525..30
1S1770	Z-Di	=1S1766:9..12V	31a	-	-
1S1771	Z-Di	=1S1766:11..14V	31a	-	-
1S1772	Z-Di	=1S1766:13..16V	31a	-	-
1S1773	Z-Di	=1S1766:15..19V	31a	-	-
1S1774	Z-Di	=1S1766:18..22V	31a	-	-
1S1775	Z-Di	=1S1766:20..27V	31a	-	-
1S1776	Z-Di	=1S1766:25..35V	31a	-	-
1S1777	Z-Di	=1S1766:30..40V	31a	-	-
1S1778	Ref-Di	8..9V	34	-	BZX51,1N4780
1S1779	Ref-Di	8..9V	34	-	BZX52,1N4781
1S178	Si-Di	=1S177:200V	32a$	-	1N4525..30
1S1780	Ref-Di	8..9V	34	-	BZX53,1N4782
1S1781	Ref-Di	8..9,5V	31a	Stl	BZX51,1N4780
1S1782	Ref-Di	8..9,5V	31a	-	BZX52,1N4781
1S1783	Ref-Di	8..9,5V	31a	-	BZX53,1N4782
1S1784	Z-Di	62V,1W	34	Stl	BZW22/..,BZX61/..,ZPY..,1N5944..56,+
1S1785	Z-Di	=1S1784:68V	34	-	-
1S1786	Z-Di	=1S1784:82V	34	-	-
1S1787	Z-Di	=1S1784:100V	34	-	-
1S1788	Z-Di	=1S1784:120V	34	-	-
1S1789	Z-Di	=1S1784:130V	34	-	-
1S179	Si-Di	=1S177:300V	32a$	-	1N4526..30
1S1790	Z-Di	=1S1784:150V	34	-	-
1S1791	Z-Di	=1S1784:180V	34	-	-
1S1792	Z-Di	=1S1784:200V	34	-	-
1S1793	Z-Di	=1S1784:220V	34	-	-
1S1794	Z-Di	=1S1784:250V	34	-	-
1S1795	Z-Di	=1S1784:300V	34	-	-
1S1796	Si-Di	SS,30V,0,1A,<4ns	31a	Hit	BA317,BAY38,BAY71,1N4148..49,+
1S1798	Si-Di	Gl-L,100V,8A(Tc=135o)	32a$	Org	BYX42/300,BYX98/300
1S1798R...1804R..	Si-Di	=1S1798..1804:	32b&	-	BYX42/..R,BYX98/..R
1S1798R..1804R...	Si-Di	-	32b&	-	BYX42/..R,BYX98/..R
1S1799	Si-Di	=1S1798:200V	32a$	-	BYX42/300,BYX98/300
1S18	Ge-Di	Uni,115V,50mA	31a	Mat	AA117..118,AA132..133
1S180	Si-Di	Dem,Uni,70V,0,1A	31a	Tos	BA147/100,BA188..190,BAY19..21,+
1S1800	Si-Di	=1S1798:300V	32a$	-	BYX42/300,BYX98/300
1S1801	Si-Di	=1S1798:400V	32a$	-	BYX42/600,BYX98/600
1S1802	Si-Di	=1S1798:600V	32a$	-	BYX42/600,BYX98/600
1S1803	Si-Di	=1S1798:800V	32a$	-	BYX42/900,BYX98/900
1S1804	Si-Di	=1S1798:1000V	32a$	-	BYX42/1000,BYX98/1000
1S1805(A)	C-Di	FM/VHF-AFC/Tuning	10	Njr	BB109,BB143,MV109,1SV50,+
1S1806(A)	C-Di	FM/VHF-AFC/Tuning	10	Njr	BB109,BB143,MV109,1SV50,+
1S1807	Si-Di	UHF-M,890MHz	31a	Tos	-
1S1808	Si-Di	Gl-L,600V,210A(Tc=105o)	73b&	Rhm	1N3740R..44R
1S1809	Si-Di	=1S1808:800V	73b&	-	1N3741R..44R
1S181	Si-Di	=1S180:120V	31a	-	BA147/150,BA189..190,BAY20..21,+
1S1810	Si-Di	=1S1808:1000V	73b&	-	1N3742R..44R
1S1811	Si-Di	=1S1808:1200V	73b&	-	1N3743R..44R
1S1812	Si-Di	=1S1808:1400V	73b&	-	1N3744R
1S1813	Si-Di	=1S1808:1600V	73b&	-	-
1S1814	Si-Di	Gl-L,600V,300A(Tc=105o)	73b&	Rhm	-
1S1815	Si-Di	=1S1814:800V	73b&	-	-
1S1816	Si-Di	=1S1814:1000V	73b&	-	-
1S1817	Si-Di	=1S1814:1200V	73b&	-	-
1S1818	Si-Di	=1S1814:1400V	73b&	-	-
1S1819	Si-Di	=1S1814:1600V	73b&	-	-

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1S182	Si-Di	=1S180:220V	31a	-	BA147/230,BAY21,BAY46,BAY88,+
1S1820	Si-Di	UHF-M,887MHz	31a	Hit	-
1S1821	Si-Di	Gl,contr.av.,800V,1A	34a$	Nec,Shi	BYW55..56,1N4248..49,1N5062,+
1S1821R...1824R..	Si-Di	=1S1821..1824:	34b&	-	→1S1821..1824
1S1821R..1824R...	Si-Di	-	34b&	-	-
1S1822	Si-Di	-	34a$	-	-
1S1823	Si-Di	-	34a$	-	-
1S1824	Si-Di	-	34a$	-	-
1S1825	Si-Di	Gl,contr.av.,800V,12A(Tc=130o)	32a$	Nec	1N4528..30
1S1829	Si-Di	Gl,Uni,800V,1A	31a	Tos	BY127,BY133,BY227,1N4006..07,+
1S183	Si-Di	=1S180:320V	31a	-	BA147/300,BAY21,BAY46,BAY88,+
1S1830	Si-Di	=1S1829:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S1831	Si-Di	Gl,2000V,0,15A	31a	Tos	BAY91,BY203/20,SHG2
1S1832	Si-Di	Gl,S,1800V,0,7A	31a	Tos	DM516
1S1834	Si-Di	Gl,S,400V,1A,<350ns	31a	Tos	BY201/4,BYX55/600,MR814,RGP10G,+
1S1835	Si-Di	=1S1834:600V	31a	-	BY201/6,BYX55/600,MR816,RGP10J,+
1S1836	Si-Di	TV-kV-Gl,18kV,2mA	31a	Tos	BY476,BY711
1S1837	Si-Di	=1S1836:25kV	31a	-	BY478,BY713
1S1838	Si-Di	=1S1836:45kV	31a	-	-
1S184	Si-Di	Dem,S,15V,0,04A	31a	Tos	BA281
1S1841	Si-Di	Gl-L,400V,25A(Tc=110o)	32	Tos	1N3765..68,1N4526..30
1S1842	Si-Di	=1S1841:600V	32	-	1N3765..68,1N4527..30
1S1843	Si-Di	=1S1841:800V	32	-	1N3766..68,1N4528..30
1S1844	Si-Di	=1S1841:1000V	32	-	1N3768,1N4529..30
1S1845	Si-Di	Gl,200V,0,5A	31a	-	BY251..255,BY226..227,BYW17/200,+
1S1845A	Si-Di	=1S1845:400V	31a	-	BY252..255,BY226..227,BYW17/400,+
1S1845B	Si-Di	=1S1845:600V	31a	-	BY253..255,BY226..227,BYW17/600,+
1S1845C	Si-Di	=1S1845:800V	31a	-	BY254..255,BY227,BYW17/800,+
1S1845D	Si-Di	=1S1845:1000V	31a	-	BY255,BY227,BYW17/1000,BYX86,+
1S1845E	Si-Di	=1S1845:1200V	31a	-	BY255,BY227,BYW17/1200,BYX87,+
1S1846(A...E)	Si-Di	=1S1845(A..E):1A	31a	-	→1S1845(A..E)
1S1846(A..E)	Si-Di	-	31a	-	-
1S1847(A...E)	Si-Di	Gl-L,200..1200V,8A(Tc=50o)	73a$	-	BYX42/..,BYX98/..
1S1847(A..E)	Si-Di	-	73a$	-	BYX42/..BYX98/..
1S1848(A...E)	Si-Di	Gl-L,200..1200V,22A(Tc=50o)	73a$	-	BYX96/..
1S1848(A..E)	Si-Di	-	73a$	-	BYX96/..
1S1849(R)	Si-Di	Dual,Gl,100V,1,5A	12p/q	Sak	(2xBY226..227,2xBY251..255,++)
1S185	Si-Di	Dem,S,15V,0,04A	31a	Tos	BA281
1S1850(R)	Si-Di	=1S1849:200V	12p/q	-	(2xBY226..227,2xBY251..255,++)
1S1851(R)	Si-Di	=1S1849:400V	12p/q	-	(2xBY226..227,2xBY252..255,++)
1S1855	Si-Di	Snap-off-Di,SS	31a	Nec	-
1S1856	Si-Di	Snap-off-Di,SS	Koax	Nec	-
1S1857	Si-Di	Snap-off-Di,SS	Koax	Nec	-
1S1858	Si-Di	Schottky-Di,SS,10V,0,03A,<1ns	Koax	Nec	BAT19,1SS88,1SS106
1S186	Ge-Di	Uni,75V,30mA	31a	Say	AA117..118,AA132..133
1S1860	Si-Di	Schottky-Di,UHF-M,855MHz,3V,30mA	31a	Nec	BA480..481,BAR19,BAT29
1S1861	Si-Di	Gl-L,1000V,40A(Tc=104o)	32	Inr	BYX56/1000,BYX97/1200
1S1862	Si-Di	Gl-L,1000V,60A(Tc=126o)	32	Inr	DS75-11B
1S1863	Si-Di	Gl-L,100V,150A(Tc=116o)	73a$	Inr	1N4587..96
1S1864	Si-Di	=1S1863:150V	73a$	-	1N4588..96
1S1865	Si-Di	=1S1863:200V	73a$	-	1N4588..96
1S1866	Si-Di	=1S1863:300V	73a$	-	1N4589..96
1S1867	Si-Di	=1S1863:400V	73a$	-	1N4590..96
1S1868	Si-Di	=1S1863:500V	73a$	-	1N4591..96
1S1869	Si-Di	=1S1863:600V	73a$	-	1N4592..96
1S187(S)	Ge-Di	Dem,40V,50mA,S:200ns	31a	Say	AA113,AA119,1N34,1N54,1N60
1S1870	Si-Di	=1S1863:800V	73a$	-	1N4593..96
1S1871	Si-Di	=1S1863:1000V	73a$	-	1N4594..96
1S1872	Si-Di	Gl-L,100V,250A(Tc=107o)	73a$	Inr	1N3735..44
1S1873	Si-Di	=1S1872:150V	73a$	-	1N3736..44
1S1874	Si-Di	=1S1872:200V	73a$	-	1N3736..44
1S1875	Si-Di	=1S1872:300V	73a$	-	1N3737..44
1S1876	Si-Di	=1S1872:400V	73a$	-	1N3738..44
1S1877	Si-Di	=1S1872:500V	73a$	-	1N3739..44

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1S1878	Si-Di	=1S1872:600V	73a$	-	1N3740..44
1S1879	Si-Di	=1S1872:800V	73a$	-	1N3741..44
1S188(AM,FM)	Ge-Di	AM/FM-Dem,40V,50mA	31a	Say	AA113,AA119,1N34,1N54,1N60,+
1S1880	Si-Di	=1S1872:1000V	73a$	-	1N3742..44
1S1881	Si-Di	=1S1872:1200V	73a$	-	1N3743..44
1S1882	Si-Di	=1S1872:1400V	73a$	-	1N3744
1S1885(A)	Si-Di	Gl,100V,1A,A=1,2A	31a	Tos	BY126..127,BY133..135,1N4002..07,+
1S1886(A)	Si-Di	=1S1885:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S1887(A)	Si-Di	=1S1885:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S1888(A)	Si-Di	=1S1885:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S188G	Ge-Di	Dem,25V,50mA	31a	-	AA113,AA119,1N34,1N54,1N60,+
1S189	Ge-Di	Dem,50V,40mA	31a	Say	AA113,AA119,1N34,1N54,1N60
1S1890	Si-Di	Gl,Uni,600V,1,2A	34a$	Tos	BY226..227,BY253..255,1N5397..99,+
1S1891	Si-Di	=1S1890:800V	34a$	-	BY227,BY254..255,1N5398..99,+
1S1892	Si-Di	=1S1890:1000V	34a	-	BY227,BY255,BYX86,1N5398..99,+
1S1893	C-Di	AFC	31a	Sak	BA124..125,BB119,1S2790,1SV50,+
1S1894(A...D)	C-Di	VHF-AFC,VHF-Tuning	31a	Sak	BB105G,BB205G,BB305G,BB505G,+
1S1894(A..D)	C-Diode	VHF-AFC,VHF-Tuning	31a	Sak	BB105G,BB205G,BB305G,BB505G..
1S1895(A...D)	C-Di	VHF-AFC,VHF-Tuning	31a	Sak	BB105G,BB205G,BB305G,BB505G,+
1S1895(A..D)	C-Diode	VHF-AFC,VHF-Tuning	31a	Sak	BB105G,BB205G,BB305G,BB505G..
1S1897	Si-Di	TV-Damper-Di,500V,1,5A,<800ns	34	Sak	BY258/500,BY298,BYV14,RGP15J,+
1S1898	Si-Di	=1S1897:800V	34	-	BY258/800,BY299,BYV15,RGP15K,+
1S1899	Si-Di	=1S1897:1000V	34	-	BY246/1000,BY299,BYV16,RGP15M,+
1S19	Ge-Di	Dem,15V,3SmA	31a	Mat	AA112..114,1N34,1N54,1N60,+
1S190	Z-Di	4,4..5,6V,0,4W	31a	Njr	BZX55/..,BZX79/..,ZPD..,1N5231..50,+
1S1901	Si-Di	TV-Damper-Di,1500V,1,5A,<1,5?s	22	Sak	BY359/1500
1S1902	Si-Di	Gl,S,500V,0,8A,<300ns	34	Sak	BY201/5,BYX55/600,RGP10J,1N4946,+
1S1903	Si-Br	Gl-Br,70V(eff),1,5A	-	Sak	B80C1500,etc.
1S1904	Si-Br	=1S1903:140V	-		B140C1500,etc.
1S1905	Si-Di	Dual,100V,1A	12p	Sak	2x(BY126..127,BY133..135,1N4002,++)
1S1905R...1907R..	Si-Di	=1S1905..1907	12q	-	→1S1905..1907
1S1905R..1907R...	Si-Di	-	12q	-	-
1S1906	Si-Di	=1S1905:200V	12p	-	2x(BY126..127,BY133..134,1N4003,++)
1S1907	Si-Di	=1S1905:400V	12p	-	2x(BY126..127,BY133..134,1N4004,++)
1S1908	Si-Di	Gl,S,100V,1,5A,<300ns	-	Sak	(BY205/100,BYV87/300,ESM181/300R,+)
1S1909	Si-Di	=1S1908:200V	-		(BY205/200,BYV87/300,ESM181/300R,+)
1S191	Z-Di	=1S190:5,4..6,6V	31a	-	-
1S1910	Si-Di	Gl,S,1300V,1A,<1?s	34b&	Sak	BY228,BY231/1400,BY400,BY448
1S1911	Si-Di	=1S1910:1500V	34b&	-	BY228,BY231/1500,BY400,BY448
1S1912	Si-Di	kV-Gl,10kV,3mA,<300ns	31a	Sak	BY509..510,BY707..709
1S1914	Si-Di	Gl,Uni,100V,1,5A	34a	Sak	BY226..227,BY251..255,1N5392..99,+
1S1915	Si-Di	=1S1914:200V	34a	-	BY226..227,BY251..255,1N5393..99,+
1S1916	Si-Di	=1S1914:400V	34a	-	BY226..227,BY252..255,1N5395..99,+
1S1917	Si-Di	=1S1914:600V	34a	-	BY226..227,BY253..255,1N5397..99,+
1S1918	Si-Di	=1S1914:800V	34a	-	BY227,BY254..255,1N5398..99,+
1S1919	Si-Di	=1S1914:1000V	34a	-	BY227,BY255,BYX87,1N5399,+
1S192	Z-Di	=1S190:6,4..7,6V	31a	-	-
1S1920	Si-Di	Gl,Uni,1200V,0,8A	34	Hit	BY133,BY227,BYX95,GP10Q,EM513
1S1921A	Si-Di	Gl,Uni,200V,0,1A	31a	Hit	BA157..159,BA147/230,BAY88..91,+
1S1921B	Si-Di	=1S1921A:400V	31a	-	BA157..159,BAY88..91,BY203/12,+
1S1921C	Si-Di	=1S1921A:600V	31a	-	BA158..159,BAY89..91,BY203/12,+
1S1921D	Si-Di	=1S1921A:800V	31a	-	BA159,BAY90..91,BY203/12,+
1S1921E	Si-Di	=1S1921A:1000V	31a	-	BA159,BAY90..91,BY203/12,+
1S1921F	Si-Di	=1S1921A:1200V	31a	-	BAY91,BY203/12,BY584,RGP01-12,+
1S1922	C-Di	AFC	31a	Njr	BA124..125,BB119,1SV114,1SV125,+
1S1923	C-Di	AFC	31a	Njr	BA124..125,BB119,1SV114,1SV125,+
1S1924	C-Di	AFC	31a	Njr	BA124..125,BB119,1SV114,1SV125,+
1S1925	Si-Di	Schottky-Di,UHF-M,5V,50mA,890MHz	31a	Njr	-
1S1926	Si-Di	Schottky-Di,UHF-M,5V,25mA,890MHz	31a	Njr	BA480..481,BAR19,BAT29
1S1927	Si-Di	Gl-L,contr.av.,2000V,7A(Tc=120o)	32b&	Fjd	-
1S1928	Si-Di	Gl-L,contr.av.,2000V,12A(Tc=120o)	32b&	Fjd	-
1S1929	Si-Di	Gl-L,contr.av.,3000V,12A(Tc=120o)	32b&	Fjd	-
1S193	Z-Di	=1S190:7,4..8,6V	31a	-	-
1S1930	Si-Di	Gl-L,contr.av.,2000V,24A(Tc=120o)	32b&	Fjd	-

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1S1931	Si-Di	Gl-L,contr.av.,3000V,24A(Tc=120o)	32b&	Fjd	-
1S1932	Si-Di	Gl-L,contr.av.,2000V,50A(Tc=120o)	73b&	Fjd	-
1S1933	Si-Di	=1S1932:3000V	73b&	Fjd	-
1S1934	Si-Di	Gl-L,100V,20A(130o)	32a$	Org	1N3765..3768,1N4525..4530
1S1934R...1939R..	Si-Di	=1S1934..1939:	32b&	-	D24/..C,1N3765R..3768R
1S1934R..1939R...	Si-Di	-	32b&	-	D24/..C,1N3765R..3768R
1S1935	Si-Di	=1S1934:200V	32a$	-	1N3765..3768,1N4525..4530
1S1936	Si-Di	=1S1934:400V	32a$	-	1N3765..3768,1N4526..4530
1S1937	Si-Di	=1S1934:600V	32a$	-	1N3765..3768,1N4527..4530
1S1938	Si-Di	=1S1934:800V	32a$	-	1N3766..3768,1N4528..4530
1S1939	Si-Di	=1S1934:1000V	32a$	-	1N3768,1N4529..4530
1S194	Z-Di	=1S190:8,4..9,6V	31a	-	-
1S1941	Si-Di	Gl,Uni,100V,0,5A	31a	Tos	BY133..135,BY226..227,1N4002..07,+
1S1942	Si-Di	=1S1941:200V	31a	-	BY133..134,BY226..227,1N4003..07,+
1S1943	Si-Di	=1S1941:400V	31a	-	BY133..134,BY226..227,1N4004..07,+
1S1944	Si-Di	=1S1941:600V	31a	-	BY133..134,BY226..227,1N4005..07,+
1S1948	Si-Di	Gl,Uni,200V,1,3A	31a	Hit	BY226..227,BY251..255,1N5393..99,+
1S1949	Si-Di	=1S1948:400V	31a	-	BY226..227,BY252..255,1N5395..99,+
1S195	Z-Di	=1S190:9,4..10,6V	31a	-	-
1S1950	Si-Di	=1S1948:600V	31a	-	BY226..227,BY253..255,1N5397..99,+
1S1951	Z-Di	31..35V,1W	31a	Hit	BZW22/C33,BZX61/C33,ZPY33,1N5937,+
1S1952	Z-Di	1,8..2,6V,1W	31a	Hit	BZW22/..,BZX61/..,ZPY..,1N5913..36,+
1S1953	Z-Di	=1S1952:2,5..3,5V	31a	-	-
1S1954	Z-Di	=1S1952:3,4..4,6V	31a	-	-
1S1955	Z-Di	=1S1952:4,4..5,6V	31a	-	-
1S1956	Z-Di	=1S1952:5,2..6,6V	31a	-	-
1S1957	Z-Di	=1S1952:6,4..7,9V	31a	-	-
1S1958	Z-Di	=1S1952:7,7..8,8V	31a	-	-
1S1959	Z-Di	=1S1952:8,5..9,6V	31a	-	-
1S196	Z-Di	=1S190:10,4..11,6V	31a	-	-
1S1960	Z-Di	=1S1952:9,4..10,6V	31a	-	-
1S1961	Z-Di	=1S1952:10,4..11,6V	31a	-	-
1S1962	Z-Di	=1S1952:11,4..12,7V	31a	-	-
1S1963	Z-Di	=1S1952:12,4..14,1V	31a	-	-
1S1964	Z-Di	=1S1952:13,8..15,6V	31a	-	-
1S1965	Z-Di	=1S1952:15,3..17,1V	31a	-	-
1S1966	Z-Di	=1S1952:16,8..19,1V	31a	-	-
1S1967	Z-Di	=1S1952:18,8..21,2V	31a	-	-
1S1968	Z-Di	=1S1952:20,8..23,3V	31a	-	-
1S1969	Z-Di	=1S1952:22,7..25,6V	31a	-	-
1S197	Z-Di	=1S190:11,4..12,6V	31a	-	-
1S1970	Z-Di	=1S1952:25,1..28,9V	31a	-	-
1S1971	Z-Di	=1S1952:28..32V	31a	-	-
1S1972(M)	Si-Di	SS,75V,0,2A,<4ns	31a	Nec,Tos	BAW62,BAX95,1N4148..49,1N4446..49+
1S1973(M)	Si-Di	SS,35V,0,1A,<4ns	31a	Nec,Tos	BA318,BAY38,BAX80,1N4148..49,+
1S198	Z-Di	=1S190:12,4..16,1V	31a	-	-
1S199	Z-Di	=1S190:15,9..20V	31a	-	-
1S1991	Diac	Ub=23..37V,Ib<0,2mA,Itsm=2A	31	Sak	1N5761,N413M,D3202Y,BR100,DO201YR
1S1992	Si-Di	Schottky-Di,30V,0,02A	31a	Nec	BAT81,HSS100..102
1S1993	Si-Di	Schottky-Di,20V,0,03A	31a	Nec	BAT81,HSS100..102
1S1994	Si-Di	Schottky-Di,30V,0,03A	31a	Nec	BAT81,HSS100..102
1S1995	Si-Di	Schottky-Di,20V,0,05A	31a	Nec	BAT81,HSS100..102
1S1996	Si-Di	Gl,Uni,200V,3A(Tc=128o)	?34a$	Hit	BY251..255,1N5402..08,(BY205/200,++)
1S1996R...1999R..	Si-Di	=1S1996..1999	?34b&	-	BY251..255,1N5402..08,(BY205/..,++)
1S1996R..1999R...	Si-Di	-	?34b&	-	BY251..255,1N5402..08,(BY205/....)
1S1997	Si-Di	=1S1996:400V	?34a$	-	BY252..255,1N5404..08,(BY205/400,++)
1S1998	Si-Di	=1S1996:600V	?34a$	-	BY253..255,1N5406..08,(BY205/600,++)
1S1999	Si-Di	=1S1996:800V	?34a$	-	BY254..255,1N5407..08,(BY205/800,++)
1S20	Ge-Di	S,30V,Ifm=0,15A,<500ns	31a	Tos	AAY27..28,1N276
1S200	Ge-Di	Dem,35V,25mA	31a	Njr	AA112..114,AA119,1N34,1N54,1N60,+
1S2000	Si-Di	Gl-L,400V,10A(Tc=128o)	32a$	Hit	1N3765..3768,1N4526..4530
1S2000R...2002R..	Si-Di	=1S2000..2002:	32b&	-	D24/..C,1N3765R..3768R
1S2000R..2002R...	Si-Di	-	32b&	-	D24/..C,1N3765R..3768R
1S2001	Si-Di	=1S2000:600V	32a$	-	1N3765..3768,1N4527..4530

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1S2002	Si-Di	=1S2000:800V	32a$	-	1N3766..3768,1N4528..4530
1S2003	Si-Di	GI-L,100V,10A(Tc=125o)	75a$	Hit	1N3492..3495
1S2003R	Si-Di	=1S2003:	75b&	-	DS25-..A,1N3492R..3495R
1S2004(R)	Si-Di	GI-L,100V,15A(Tc=110o)	-	Hit	(BY205/100,BY249/300,BYV87/300,++)
1S2005	Si-Di	GI-L,400V,20A(Tc=100o)	32a$	Hit	1N3765..3768,1N4526..4530
1S2005R...2007R..	Si-Di	=1S2005..2007:	32b&	-	D24/..C,1N3765R..3768R
1S2005R..2007R...	Si-Di	-	32b&	-	D24/..C,1N3765R..3768R
1S2006	Si-Di	=1S2005:600V	32a$	-	1N3765..3768,1N4527..4530
1S2007	Si-Di	=1S2005:800V	32a$	-	1N3766..3768,1N4528..4530
1S2008(R)	Si-Di	GI-L,100V,75A(Tc=120o)	-	Hit	-
1S2009(R)	Si-Di	=1S2008:200V	-		-
1S201	Ge-Di	FM/VHF,20V,48..72/2..6pF(0,5/10V)	2	Njr	-
1S2010(R)	Si-Di	=1S2008:300V	-		-
1S2011	Si-Di	GI-L,1000V,20A(Tc=100o)	32a$	Hit	1N3768,1N4529..4530
1S2011R	Si-Di	=1S2011:	32b&	-	D24/1200C,1N3768R
1S2012	Si-Di	GI-L,200V,100A(Tc=104o)	73a$	Hit	1N3289..3297,1N4588..4596
1S2013	Si-Di	=1S2012:400V	73a$	-	1N3291..3297,1N4590..4596
1S2014	Si-Di	=1S2012:600V	73a$	-	1N3293..3297,1N4592..4596
1S2015	Si-Di	=1S2012:800V	73a$	-	1N3294..3297,1N4593..4596
1S2016	Si-Di	=1S2012:1000V	73a$	-	1N3295..3297,1N4594..4596
1S2017	Si-Di	=1S2012:1300V	73a$	-	1N3297,1N4596
1S2018	Si-Di	=1S2012:1500V	73a$	-	-
1S2019	Si-Di	GI-L,200V,100A(Tc=90o)	73a$	Hit	1N3289..3297,1N4588..4596
1S202	Ge-Di	FM/VHF,20V,28..45/1,5..4,5pF(0,5/10V)	2	Njr	-
1S2020	Si-Di	=1S2019:400V	73a$	-	1N3291..3297,1N4590..4596
1S2021	Si-Di	=1S2019:600V	73a$	-	1N3293..3297,1N4592..4596
1S2022	Si-Di	=1S2019:800V	73a$	-	1N3294..3297,1N4593..4596
1S2023	Si-Di	=1S2019:1000V	73a$	-	1N3295..3297,1N4594..4596
1S2024	Si-Di	=1S2019:1300V	73a$	-	1N3297,1N4596
1S2025	Si-Di	=1S2019:1500V	73a$	-	-
1S2026(R)	Si-Di	GI-L,100V,150A(Tc=110o)	-	Hit	-
1S2027(R)	Si-Di	=1S2026:200V	-		-
1S2028(R)	Si-Di	=1S2026:300V	-		-
1S2029	Si-Di	GI-L,800V,30A(Tc=95o)	32a$	Hit	1N3766..3768,1N4528..4530
1S2029R	Si-Di	=1S2029:	32b&	-	D34/..C,1N3766R..3768R
1S203	Ge-Di	FM/VHF,20V,12..18/1..3pF(0,5/10V)	2	Njr	-
1S2030(A)	Z-Di	3V,0,4W,10%,(A=5%)	31a	Tix	BZX55/..BZX83/..ZPD..1N5225..57
1S2030(A)[Texas]	Z-Di	3V,0,4W,10%,(A=5%)	31a	Tix	BZX55/..,BZX83/..,ZPD..,1N5225..57
1S2030(R)	Si-Di	GI-L,100V,250A(Tc=120o)	-	Hit	-
1S2031(R)	Si-Di	=1S2030:200V	-		-
1S2032(R)	Si-Di	=1S2030:300V	-		-
1S2033	Si-Di	GI-L,800V,50A(Tc=60o)	73a$	Hit	1N3294..3297
1S2033(A)	Z-Di	=1S2030[Texas]:3,3V	31a	Tix	→1S2030
1S2033(A)[Texas]	Z-Di	=1S2030[Texas]:3,3V	31a	Tix	→1S2030
1S2033R	Si-Di	=1S2033:	73b&	-	1N3294R..3297R
1S2034	Si-Di	GI-L,200V,20A(Tc=115o)	75a$	Hit	1N3493..3295
1S2034R...2035R..	Si-Di	=1S2034:	75b&	-	DS25-..A,1N3493R..3295R
1S2034R..2035R...	Si-Di	-	75b&	-	DS25-..A,1N3493R..3295R
1S2035	Si-Di	=1S2034:300V	75a$	-	1N3494..3295
1S2036	Si-Di	GI-L,200V,10A(Tc=125o)	75a$	Hit	1N3493..3295
1S2036(A)	Z-Di	=1S2030[Texas]:3,6V	31a	Tix	→1S2030
1S2036(A)[Texas]	Z-Di	=1S2030[Texas]:3,6V	31a	Tix	→1S2030
1S2036R...2037R..	Si-Di	=1S2036:	75b&	-	DS25-..,1N3493R..3295R
1S2036R..2037R...	Si-Di	-	75b&	-	DS25-..1N3493R..3295R
1S2037	Si-Di	=1S2036:300V	75a$	-	1N3494..3295
1S2038	Si-Di	GI-L,2500V,300A(Tc=90o)	73b&	Hit	-
1S2039	Si-Di	=1S2038:3000V	73b&	-	-
1S2039(A)	Z-Di	=1S2030[Texas]:3,9V	31a	Tix	→1S2030
1S2039(A)[Texas]	Z-Di	=1S2030[Texas]:3,9V	31a	Tix	→1S2030
1S204	Si-Di	GI,Uni,250V,0,1A	31a	Njr	BA157..159,BA199/250,BAY88..90,+
1S2040	Si-Di	=1S2038:4000V	73b&	-	-
1S2041	Si-Di	GI-L,2000V,800A(Tc=100o)	-	Hit	-
1S2042	Si-Di	=1S2041:2500V	-		-
1S2043	Z-Di	1,8..2,6V,10W(Tc=115°)	32b&	Hit	BZX98/..BZY93/..ZX..1N2970..90

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1S2043(A)	Z-Di	=1S2030[TexμS]:4,3V	31a	Tix	→1S2030
1S2043(A)[Texas]	Z-Di	=1S2030[Texas]:4,3V	31a	Tix	→1S2030
1S2043[	Z-Di	1,8..2,6V,10W(Tc=115°)	32b&	Hit	BZX98/..BZY93/..ZX..1N2970..90
1S2043[Hitachi]	Z-Di	1,8..2,6V,10W(Tc=115o)	32b&	Hit	BZX98/..,BZY93/..,ZX..,1N2970..90
1S2044	Z-Di	=1S2043[Hitachi]:2,5..3,5V	32b&	Hit	-
1S2044[Hitachi]	Z-Di	=1S2043[Hitachi]:2,5..3,5V	32b&	-	-
1S2045	Z-Di	=1S2043[Hitachi]:3,4..4,6V	32b&	Hit	-
1S2045[Hitachi]	Z-Di	=1S2043[Hitachi]:3,4..4,6V	32b&	-	-
1S2046	Z-Di	=1S2043[Hitachi]:4,4..5,4V	32b&	Hit	-
1S2046[Hitachi]	Z-Di	=1S2043[Hitachi]:4,4..5,4V	32b&	-	-
1S2047	Z-Di	=1S2043[Hitachi]:5,2..6,8V	32b&	Hit	→1S2043
1S2047(A)	Z-Di	=1S2030[TexμS]:4,7V	31a	Tix	→1S2030
1S2047(A)[Texas]	Z-Di	=1S2030[Texas]:4,7V	31a	Tix	→1S2030
1S2047[Hitachi]	Z-Di	=1S2043[Hitachi]:5,2..6,8V	32b&	Hit	→1S2043
1S2048	Z-Di	=1S2043[Hitachi]:6,2..7,9V	32b&	Hit	-
1S2048[Hitachi]	Z-Di	=1S2043[Hitachi]:6,2..7,9V	32b&	-	-
1S2049	Z-Di	=1S2043[Hitachi]:7,7..8,7V	32b&	Hit	-
1S2049[Hitachi]	Z-Di	=1S2043[Hitachi]:7,7..8,7V	32b&	-	-
1S205	Si-Di	=1S204:350V	31a	-	BA157..159,BA199/350,BAY88..90,+
1S2050	Z-Di	=1S2043[Hitachi]:8,5..9,6V	32b&	Hit	-
1S2050[Hitachi]	Z-Di	=1S2043[Hitachi]:8,5..9,6V	32b&	-	-
1S2051	Z-Di	=1S2043[Hitachi]:9,4..10,6V	32b&	Hit	→1S2043
1S2051(A)	Z-Di	=1S2030[TexμS]:5,1V	31a	Tix	→1S2030
1S2051(A)[Texas]	Z-Di	=1S2030[Texas]:5,1V	31a	Tix	→1S2030
1S2051[Hitachi]	Z-Di	=1S2043[Hitachi]:9,4..10,6V	32b&	Hit	→1S2043
1S2052	Z-Di	=1S2043[Hitachi]:10,4..11,6V	32b&	Hit	-
1S2052[Hitachi]	Z-Di	=1S2043[Hitachi]:10,4..11,6V	32b&	-	-
1S2053	Z-Di	=1S2043[Hitachi]:11,4..12,7V	32b&	Hit	-
1S2053[Hitachi]	Z-Di	=1S2043[Hitachi]:11,4..12,7V	32b&	-	-
1S2054	Z-Di	=1S2043[Hitachi]:12,4..14,1V	32b&	Hit	-
1S2054[Hitachi]	Z-Di	=1S2043[Hitachi]:12,4..14,1V	32b&	-	-
1S2055	Z-Di	=1S2043[Hitachi]:13,5..15,6V	32b&	Hit	-
1S2055[Hitachi]	Z-Di	=1S2043[Hitachi]:13,5..15,6V	32b&	-	-
1S2056	Z-Di	=1S2043[Hitachi]:15,3..17,1V	32b&	Hit	→1S2043
1S2056(A)	Z-Di	=1S2030[TexμS]:5,6V	31a	Tix	→1S2030
1S2056(A)[Texas]	Z-Di	=1S2030[Texas]:5,6V	31a	Tix	→1S2030
1S2056[Hitachi]	Z-Di	=1S2043[Hitachi]:15,3..17,1V	32b&	Hit	→1S2043
1S2057	Z-Di	=1S2043[Hitachi]:16,8..19,1V	32b&	Hit	-
1S2057[Hitachi]	Z-Di	=1S2043[Hitachi]:16,8..19,1V	32b&	-	-
1S2058	Z-Di	=1S2043[Hitachi]:18,8..21,2V	32b&	Hit	-
1S2058[Hitachi]	Z-Di	=1S2043[Hitachi]:18,8..21,2V	32b&	-	-
1S2059	Z-Di	=1S2043[Hitachi]:20,8..23,3V	32b&	Hit	-
1S2059[Hitachi]	Z-Di	=1S2043[Hitachi]:20,8..23,3V	32b&	-	-
1S206	Si-Di	=1S204:450V	31a	-	BA158..159,BA199/450,BAY89..90,+
1S2060	Z-Di	=1S2043[Hitachi]:22,7..25,6V	32b&	Hit	-
1S2060[Hitachi]	Z-Di	=1S2043[Hitachi]:22,7..25,6V	32b&	-	-
1S2061	Z-Di	=1S2043[Hitachi]:25,1..28,9V	32b&	Hit	-
1S2061[Hitachi]	Z-Di	=1S2043[Hitachi]:25,1..28,9V	32b&	-	-
1S2062	Z-Di	=1S2043[Hitachi]:28..32V	32b&	Hit	-
1S2062(A)	Z-Di	=1S2030[TexμS]:6,2V	31a	Tix	→1S2030
1S2062(A)[Texas]	Z-Di	=1S2030[Texas]:6,2V	31a	Tix	→1S2030
1S2062[Hitachi]	Z-Di	=1S2043[Hitachi]:28..32V	32b&	-	-
1S2063	Si-Di	GI,Uni,800V,1,3A	31a	Hit	BY227,BY254..2S5,1N5398..99,+
1S2064	Trigger-Di	Ub=28..38V,Ib<0,2mA,Itsm=2A	31l	Hit	-
1S2067	Ref-Diode	8,5V	31a	Njr	BZX51,1N4780
1S2067[Njr]	Ref-Di	8,5V	31a	Njr	BZX51,1N4780
1S2068	Ref-Diode	8,5V	31a	Njr	BZX51,1N4781
1S2068(A)	Z-Di	=1S2030[TexμS]:6,8V	31a	Tix	→1S2030
1S2068(A)[Texas]	Z-Di	=1S2030[Texas]:6,8V	31a	Tix	→1S2030
1S2068[	Ref-Diode	8,5V	31a	Njr	BZX51,1N4781
1S2068[Njr]	Ref-Di	8,5V	31a	Njr	BZX51,1N4781
1S2069	Ref-Diode	8,5V	31a	Njr	BZX53,1N4782
1S2069[Njr]	Ref-Di	8,5V	31a	Njr	BZX53,1N4782
1S207	Si-Di	=1S204:550V	31a	-	BA158..159,BA199/550,BAY89..90,+

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1S2070	Si-Di	SS,50V,45mA,<3ns	31a	Fui	BA318,BAY38,1N4305,1N4148..49,+
1S2071	Si-Di	SS,22V,45mA,<5ns	31a	Fui	BA318,BAY38,1N4305,1N4148..49,+
1S2072	Si-Di	SS,80V,0,2A,<6ns	31a	Fui	BAW62,BAX95,1N4148..49,1N4446..49+
1S2074H	Si-Di	SS,50V,0,15A,<4ns	31a	Hit	BAW62,BAX95,1N4148..49,1N4446..49+
1S2075(A)	Z-Di	=1S2030[TexμS]:7,5V	31a	Tix	→1S2030
1S2075(A)	Z-Di	7,5V,0,4W,10%,(A=5%)	31a	Tix	→1S2030
1S2075(A)[Texas]	Z-Di	=1S2030[Texas]:7,5V	31a	Tix	→1S2030
1S2075K	Si-Di	SS,35V,0,1A,<8ns	31a	Hit	BA318,BAY38,1N4305,1N4148..49,+
1S2076	Si-Di	Dem,SS,35V,0,15A,<8ns,40MHz	31a	Hit	BAW62,BAX95,1N4148..49,1N4446..49+
1S2076A	Si-Di	=1S2076:70V	31a	-	BAW62,BAX95,1N4148..49,1N4446..49+
1S208	Si-Di	GI,Uni,250V,0,4A	34	Njr	BY126..127,BY133..134,1N4004..07,+
1S2080	Si-Di	-	31a	Hitachi	BY133..135,BY226..227,1N4003..07..
1S2080[Hitachi]	Si-Di	GI,Uni,200V,1,1A	31a	Hit	BY133..135,BY226..227,1N4003..07,+
1S2081	Si-Di	-	31a	Hitachi	BY133..135,BY226..227,1N4003..07..
1S2081[Hitachi]	Si-Di	=1S2080[Hitachi]:400V	31a	-	BY133..135,BY226..227,1N4003..07,+
1S2082	Si-Di	-	31a	Hitachi	BY133..135,BY226..227,1N4003..07..
1S2082(A)	Z-Di	=1S2030[TexμS]:8,2V	31a	Tix	→1S2030
1S2082(A)[Texas]	Z-Di	=1S2030[Texas]:8,2V	31a	Tix	→1S2030
1S2082[Hitachi]	Si-Di	=1S2080[Hitachi]:600V	31a	-	BY133..135,BY226..227,1N4003..07,+
1S2083	Si-Di	GI-L,100V,20A(Tc=115o)	75a$	Hit	1N3492..3495
1S2083R	Si-Di	=1S2083:	75b&	-	DS25-..,1N3492R..3495R
1S2084	Si-Di	GI-L,1000V,10A(Tc=128o)	32a$	Hit	1N3768,1N4529..4530
1S2085(A)	C-Di	VHF/UHF-AFC,Tuning,28V,2..3pF(25V)	31a	Nec	BB105,BB205,BB305,BB405,BB505+
1S2086(A)	C-Di	VHF/UHF-AFC,Tuning,28V,2..3pF(25V)	31a	Nec	BB105,BB205,BB305,BB405,BB505+
1S2087(A)	C-Di	VHF/UHF-AFC,Tuning,28V,2..3pF(25V)	31a	Nec	BB105,BB205,BB305,BB405,BB505+
1S2088(A)	C-Di	VHF/UHF-AFC,Tuning,28V,2..3pF(25V)	31a	Nec	BB105,BB205,BB305,BB405,BB505+
1S2089	C-Di	VHF/UHF-O/M/AFC,Tuning,30V,2..3pF	Koax	Nec	-
1S209	Si-Di	=1S208:450V	34	-	BY126..127,BY133..134,1N4005..07,+
1S2090	C-Di	UHF-AFC,20V,3..6pF(5V)	31a	Hit	BA121,BB117,BB417,1SV89
1S2091	Si-Di	-	31a	Toshiba	BA195,BA197..198,BAV20..21..
1S2091(A)	Z-Di	=1S2030[TexμS]:9,1V	31a	Tix	→1S2030
1S2091(A)[Texas]	Z-Di	=1S2030[Texas]:9,1V	31a	Tix	→1S2030
1S2091[Toshiba]	Si-Di	CTV-HA-Diskr.,175V,0,03A,<100ns	31a	Tos	BA195,BA197..198,BAV20..21,+
1S2092	Si-Di	Uni,125V,0,03A,<100ns	31a	Tos	BA195,BA197..198,BAV19..21,+
1S2093	Diac	Ub=26..38V,Ib<0,05mA,Itsm=2A	31l	Tos	1N5761,N413M,BR100,D3202Y,D0201YR
1S2094	Si-Di	VHF/UHF-AFC,18V,7..11pF(4V)	31a	Tos	BA121,BB117,BB417,1SV89
1S2095	Si-Di	SS,55V,0,25A,<8ns	31a	Tos	BAW62,BAX95,1N4148..49,1N4446..49+
1S2095A	Si-Di	=1S2095:75V	31a	-	BAW62,BAX95,1N4148..49,1N4446..49+
1S2097	Si-Di	SS,225V,0,03A,<4ns	31a	Tos	-
1S2098	Si-Di	SS,175V,0,04A,<4ns	31a	Tos	-
1S2099	Si-Di	SS,125V,0,05A,<4ns	31a	Tos	BA203
1S21	Ge-Di	Dual-GI,380V,0,3A	-	Tos	-
1S210	Si-Di	=1S208:650V	34	-	BY127,BY133,BY227,1N4006..07,+
1S2100(A)	Z-Di	=1S2030[TexμS]:10V	31a	Tix	→1S2030
1S2100(A)[Texas]	Z-Di	=1S2030[Texas]:10V	31a	Tix	→1S2030
1S2107(A)	Z-Di	3,9V,0,25W,10%,(A=5%)	31a	Tos	BZX55/..BZX79/..ZPD..1N5228..48..
1S2107(A)[Tosh.]	Z-Di	3,9V,0,25W,10%,(A=5%)	31a	Tos	BZX55/..,BZX79/..,ZPD..,1N5228..48,+
1S2108(A)	Z-Di	=1S2107[TμSh.]:4,3V	31a	Tos	-
1S2108(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:4,3V	31a	-	-
1S2109(A)	Z-Di	=1S2107[TμSh.]:4,7V	31a	Tos	-
1S2109(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:4,7V	31a	-	-
1S211	Si-Di	=1S208:850V	34	-	BY127,BY133,BY227,1N4007,+
1S2110(A)	Z-Di	=1S2030[Texas]:11V	31a	Tis	→1S2030
1S2110(A)	Z-Di	=1S2107[Tosh.]:5,1V	31a	Tos	→1S2107
1S2110(A)[Texas]	Z-Di	=1S2030[Texas]:11V	31a	Tix	→1S2030
1S2110(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:5,1V	31a	Tos	→1S2107
1S2111(A)	Z-Di	=1S2107[TμSh.]:5,6V	31a	Tos	-
1S2111(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:5,6V	31a	-	-
1S2112(A	Z-Di	6,2V,0,25W,10%,(A=5%)	31a	Tos	-
1S2112(A)	Z-Di	=1S2107[TμSh.]:6,2V	31a	Tos	-
1S2112(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:6,2V	31a	-	-
1S2113(A)	Z-Di	=1S2107[TμSh.]:6,8V	31a	Tos	-
1S2113(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:6,8V	31a	-	-
1S2114(A)	Z-Di	=1S2107[TμSh.]:7,5V	31a	Tos	-

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1S2114(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:7,5V	31a	-	-
1S2115(A)	Z-Di	=1S2107[TμSh.]:8,2V	31a	Tos	-
1S2115(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:8,2V	31a	-	-
1S2116(A)	Z-Di	=1S2107[TμSh.]:9,1V	31a	Tos	-
1S2116(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:9,1V	31a	-	-
1S2117(A)	Z-Di	=1S2107[TμSh.]:10V	31a	Tos	-
1S2117(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:10V	31a	-	-
1S2118(A)	Z-Di	=1S2107[TμSh.]:11V	31a	Tos	-
1S2118(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:11V	31a	-	-
1S2119(A)	Z-Di	=1S2107[TμSh.]:12V	31a	Tos	-
1S2119(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:12V	31a	-	-
1S212	Ref-Di	8..9V,0,3W,n0,01%/oC	?34	Tos	-
1S2120(A)	Z-Di	=1S2107[Tosh.]:13V	31a	Tos	→1S2107
1S2120(A)	Z-Di	12V,0,4W,10%,(A=5%)	31a	Tix	→1S2030
1S2120(A)[Texas]	Z-Di	=1S2030[Texas]:12V	31a	Tix	→1S2030
1S2120(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:13V	31a	Tos	→1S2107
1S2121(A)	Z-Di	=1S2107[TμSh.]:15V	31a	Tos	-
1S2121(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:15V	31a	-	-
1S2122(A)	Z-Di	=1S2107[TμSh.]:16V	31a	Tos	-
1S2122(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:16V	31a	-	-
1S2123(A	Z-Di	=1S2107[TμSh.]:18V	31a	Tos	-
1S2123(A)	Z-Di	=1S2107[Tosh.]:18V	31a	Tos	-
1S2123(A)[Tosh.]	Z-Di	=1S2107[Tosh.]:18V	31a	-	-
1S2124	Si-Di	GI,Uni,300V,0,5A	31a	Nec	BY126..127,BY133..134,1N4004..07,+
1S2125	Z-Di	5,4..6,6V,0,25W	2	Nec	BZX55/..,BZX79/..,ZPD..,1N5232..43,+
1S2126	Z-Di	=1S2125:7,5..10V	2	Nec	-
1S2127	Z-Di	=1S212S:10,8..13,2V	2	Nec	-
1S2128	Z-Di	5,4..6,6V,1W	34	Nec	BZW22/..BZX61/..ZPY..1N5919..53..
1S2128[NEC]	Z-Di	5,4..6,6V,1W	34	Fui,Nec	BZW22/..,BZX61/..,ZPY..,1N5919..53,+
1S2129	Z-Di	=1S2128[NEC]:7,5..10V	34	Nec	-
1S2129[NEC]	Z-Di	=1S2128[NEC]:7,5..10V	34	-	-
1S213	Ref-Di	8..9V,0,3W,n0,005%/oC	?34	Tos	-
1S2130	Z-Di	=1S2128[NEC]:10,8..13,2V	34	Nec	-
1S2130(A)	Z-Di	=1S2030[TexμS]:13V	31a	Tix	→1S2030
1S2130(A)[Texas]	Z-Di	=1S2030[Texas]:13V	31a	Tix	→1S2030
1S2130[NEC]	Z-Di	=1S2128[NEC]:10,8..13,2V	34	-	-
1S2131	Z-Di	=1S2128[NEC]:17..20V	34	Nec	→1S2128
1S2131[NEC]	Z-Di	=1S2128[NEC]:17..20V	34	Fui,Nec	→1S2128
1S2132	Z-Di	=1S2128[NEC]:80..115V	34	Nec	-
1S2132[NEC]	Z-Di	=1S2128[NEC]:80..115V	34	-	-
1S2133	Z-Di	=1S2128[NEC]:115..140V	34	Nec	-
1S2133[NEC]	Z-Di	=1S2128[NEC]:115..140V	34	-	-
1S2134	Si-Di	SS,40V,45mA,<7ns	31a	Fui,Hit,Nec	BA318,BAY38,1N4305,1N4148..49,+
1S2135	Si-Di	SS,70V,0,2SA,<7ns	31a	Fui,Hit,Nec	BAW62,BAX95,1N4446..49,1N4148..49+
1S2136	Z-Di	5,4..6,6V,0,25W	2	Hit	BZX55/..,BZX79/..,ZPD..,1N5232..43,+
1S2137	Z-Di	=1S2136:7,5..10V	2	-	-
1S2138	Z-Di	=1S2136:10,8..13,2V	2	-	-
1S2139(A..C)	C-Di	VHF-AFC/Tuning,15V,4..16pF(4V)	31a	Njr	BB105,BB205,BB305,BB405,BB505+
1S214	Ref-Di	8..9V,0,3W,n0,002%/oC	?34	Tos	-
1S2140	Si-Di	SS,60V,0,25A,<6ns	31a	Fui	BAW62,BAX95,1N4446..49,1N4148..49+
1S2142	C-Di	Dual,FM/VHF,Tuning/AFC,20V,10..20pF	12p	Sak	BB104,BB204,BB304,MV104,+
1S2143	C-Di	Dual,FM/VHF,Tuning/AFC,30V,10..20pF	12p	Sak	BB104,BB204,BB304,MV104,+
1S2144A..C	Si-Di	SS,40V,0,15A,5ns	31a	Sak	BA200..201,BAW46,BAX80,1N4148..49,+
1S2145	Si-Di	SS,90V,0,1A,<5ns	31a	Sak	BA219,1N4446..49,1N4148..49
1S2147(A..D)	C-Di	VHF-AFC/Tuning,40V,2,3..6,7pF(10V)	31a	Sak	BA105,BA205,BA305,BA405,BA505+
1S2148	Si-Di	GI,Dual,100V,1,5A	12p	Sak	2x(BY226..227,BY251..255,1N5392..99++)
1S2148R...2149R..	Si-Di	=1S2148:	12q	-	2x(BY226..227,BY251..255,1N5393..99++)
1S2148R..2149R...	Si-Di	-	12q	-	2x(BY226..227,BY251..255,1N5393..99..)
1S2149	Si-Di	=1S2148:200V	12p	-	2x(BY226..227,BY251..255,1N5393..99++)
1S215	Ref-Di	8,9..9,9V,0,3W,n0,01%/oC	?34	Tos	-
1S2150(A)	Z-Di	=1S2030[TexμS]:15V	31a	Tix	→1S2030
1S2150(A)[Texas]	Z-Di	=1S2030[Texas]:15V	31a	Tix	→1S2030
1S216	Ref-Di	8,9..9,9V,0,3W,n0,005%/oC	?34	Tos	-
1S2160(A)	Z-Di	=1S2030[TexμS]:16V	31a	Tix	→1S2030

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1S2160(A)[Texas]	Z-Di	=1S2030[Texas]:16V	31a	Tix	→1S2030
1S217	Ref-Di	8,9..9,9V,0,3W,n0,002%/oC	?34	Tos	-
1S2175	GaAs-Di	SS,7,5V,0,05A	Koax	Nec	-
1S2176	Si-Di	kV-Gl,6kV,0,1A,<500ns	?31a	Org	BYX90,1N5183
1S2177	Si-Di	kV-Gl,6kV,0,3A,<500ns	?31a	Org	-
1S2178	Si-Di	kV-Gl,6kV,0,5A,<500ns	?31a	Org	-
1S2179	Si-Di	Gl,S,1200V,2A,<500ns	?31a	Org	BY228,BY246/1200,BY448,BY458
1S218	Si-Di	SS,40V,0,04A,<2ns	31a	Tos	BA218,BAX13,BAX91,1N4148..49,+
1S2180	Si-Di	-	?31a	Org	1N3052
1S2180(A)	Z-Di	=1S2030[TexμS]:18V	31a	Tix	→1S2030
1S2180(A)[Texas]	Z-Di	=1S2030[Texas]:18V	31a	Tix	→1S2030
1S2180[Origin]	Si-Di	kV-Gl,12kV,0,1A,<500ns	?31a	Org	1N3052
1S2181	Si-Di	-	?31a	Org	-
1S2181[Origin]	Si-Di	kV-Gl,36kV,0,1A,<500ns	?31a	Org	-
1S2182	Si-Di	-		Org	1N3061
1S2182[Origin]	Si-Di	kV-Gl,30kV,0,1A,<500ns	-	Org	1N3061
1S2186	C-Di	VHF/UHF-Band-S,20V,0,1A,<2pF(10V)	31a	Tos	BA244,BA282,BA284,BA482
1S2187	Si-Di	Schottky-Di,UHF-M,2V,30mA,900MHz	31a	Tos	BA480..481,BAT19,BAT29
1S2188	C-Di	AFC,Tuning,20V,9,5pF(4V)	31a	Hit	-
1S219	Ge-Di	TV-Damper-Di,300V,10A(ss)	?34a$	Tos	-
1S2190	Ref-Di	7,7..8,7V	2c	Nec	BZX51,1N4780
1S2191	Ref-Di	7,7..8,7V	2c	-	BZX52,1N4781
1S2192	Ref-Di	7,7..8,7V	2c	-	BZX53,1N4782
1S2193	Ref-Di	7,7..8,7V	2c	-	BZX54,1N4783
1S2194	Z-Di	5,4..6,6V,0,25W	31a	Nec	BZX55/..,BZX79/..,ZPD..,1N5232..43,+
1S2195	Z-Di	=1S2194:7,5..10V	31a	-	-
1S2196	Z-Di	=1S2194:10,8..13,2V	31a	-	-
1S2197(A)	C-Di	AFC,Tuning,20V,19<24pF(10V)	31a	Hit	-
1S2198	Si-Di	Schottky-Di,UHF-M,5V,30mA,855MHz	31a	Nec	BA480..481,BAR19,BAT29
1S2199	Ge-Diode	Tunnel-Di,Fast-Sw,11mA,Ip=9..11mA,<4Ω	34	Nec	-
1S2199[NEC]	Ge-Di	Tunnel-Di,SS,11mA,Ip=9..11mA,<4e	34	Nec	-
1S22	Ge-Di	Gl,380V,0,3A	-	Tos	-
1S220	Z-Di	4,5V,10%,1W	34a$	Tos	BZW22/..,BZX61/..,ZPY..,1N5917..53,+
1S2200	Ge-Diode	Tunnel-Di,Fast-Sw,20mA,Ip=9..11mA,<3Ω	34	Nec	-
1S2200(A)	Z-Di	=1S2030[TexμS]:20V	31a	Tix	→1S2030
1S2200(A)[Texas]	Z-Di	=1S2030[Texas]:20V	31a	Tix	→1S2030
1S2200[NEC]	Ge-Di	Tunnel-Di,SS,20mA,Ip=9..11mA,<3e	34	Nec	-
1S2204	Si-Di	SS,70V,0,2A,<7ns	31a	Nec	BAW62,BAX95,1N4446..49,1N4148..49+
1S2206	C-Di	UHF-AFC,27V,11o17/3,8o6,4pF(2/10V)	71a(4mm)	Nec	BA121,BB117,BB417,1SV89
1S2207	C-Di	VHF-AFC,27V,11o17/3,8o6,4pF(2/10V)	71a(4mm)	Nec	BA125,BB119,1SV114,1SV125
1S2208	C-Di	UHF-Tuning,30V,11o12,7/2o2,3pF(3/25V)	71a(4mm)	Nec	BB105,BB205,BB305,BB405,BB505+
1S2209	C-Di	VHF-Tuning,30V,10,3o13/2o2,5pF(3/25V)	71a(4mm)	Nec	BB105,BB205,BB305,BB405,BB505+
1S221	Z-Di	=1S220:5,5V	34a$	-	-
1S2210	Si-Di	Schottky-Di,SS,11V,0,02A	31a	Nec	BAT19,1SS88,1SS106
1S2211	Si-Di	Schottky-Di,SS,33V,35mA	31a	Nec	BAT81
1S2212	Si-Di	S,30V,0,1A,<100ns	31a	Nec	BAV17..20,BAX90,BAX94,1N3070,+
1S222	Z-Di	=1S220:6,5V	34a$	-	-
1S2220(A)	Z-Di	=1S2030[TexμS]:22V	31a	Tix	→1S2030
1S2220(A)[Texas]	Z-Di	=1S2030[Texas]:22V	31a	Tix	→1S2030
1S2222	C-Di	VHF/UHF-Band-S,30V,0,1A,<1pF(15V)	71a(4mm)	Nec	BA244,BA282,BA284,BA482
1S2223	Si-Di	Dual,Gl,100V,1,8A	12p	Inr	2x(BY251..255,BY259/150,1N5060..62++)
1S2223R...2225R	Si-Di	=1S2223:	12q	-	2x(BY251..255,BY259/..,1N5060..62++)
1S2223R..2225R	Si-Di	-	12q	-	2X(BY251..255,BY259/..1N5060..62..)
1S2224	Si-Di	=1S2223:200V	12p	-	2x(BY251..255,BY259/300,1N5060..62++)
1S2225	Si-Di	=1S2223:400V	12p	-	2x(BY252..255,BY259/600,1N5060..62++)
1S2226	Si-Di	Gl,Uni,100V,1A	31a	Inr	BY126..127,BY133..135,1N4002..07,+
1S2227	Si-Di	=1S2226:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S2228	Si-Di	=1S2226:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S2229	Si-Di	=1S2226:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S223	Z-Di	=1S220:7,5V	34a$	-	-
1S2230	Si-Di	=1S2226:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S2231	Si-Di	=1S2226:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S2233	Si-Di	Gl,Uni,600V,1,5A	34b&	Tos	BY226..227,BY253..255,1N5397..99,+
1S2234	Si-Di	=1S2233:800V	34b&	-	BY227,BY254..255,1N5398..99,+

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1S2235	Si-Di	=1S2233:1000V	34b&	-	BY227,BY255,BYX86,1N5399,+
1S2236	C-Di	FM-AFC,15V,7..14pF(4V)	31a	Tos	BA111,BA124,1S2790,1SV50,+
1S2237(B)	Si-Di	kV-Gl,18kV,2mA,<250ns	-	Tos	BY476,BY711
1S2238	Si-Di	-	31a	Hitachi	BYW53..56,1N5060..5062
1S2238[Hitachi]	Si-Di	Gl,contr.av.,400V,1,3A	31a	Hit	BYW53..56,1N5060..5062
1S2239	Si-Di	-	31a	Hitachi	BYW54..56,1N5061..5062
1S2239[Hitachi]	Si-Di	=1S2238:600V	31a	-	BYW54..56,1N5061..5062
1S224	Z-Di	=1S220:8,5V	34a$	-	-
1S2240	Si-Di	-	31a	Hitachi	BYW55..56,1N5062
1S2240(A)	Z-Di	=1S2030[TexμS]:24V	31a	Tix	→1S2030
1S2240(A)[Texas]	Z-Di	=1S2030[Texas]:24V	31a	Tix	→1S2030
1S2240[Hitachi]	Si-Di	=1S2238:800V	31a	-	BYW55..56,1N5062
1S2241	Si-Di	Gl,contr.av.,400V,1,1A	31a	Hit	BYW53..56,1N5060..5062
1S2242	Si-Di	=1S2241:600V	31a	-	BYW54..56,1N5061..5062
1S2243	Si-Di	=1S2241:800V	31a	-	BYW55..56,1N5062
1S2244	Si-Di	Gl,S,200V,0,4A,<800ns	31a	Hit	BA157..159,BY204/4,BY206..207,+
1S2245	Si-Di	=1S2244:400V	31a	-	BA157..159,BY204/4,BY207,+
1S2246	Si-Di	=1S2244:600V	31a	-	BA158..159,BY204/8,BY207,+
1S2247	Si-Di	Gl-L,500V,600A(Tc=90o)	-	Mit	-
1S2248	Si-Di	=1S2247:600V	-		-
1S2249	Si-Di	=1S2247:800V	-		-
1S225	Z-Di	=1S220:9,5V	34a$	-	-
1S2250	Si-Di	=1S2247:1000V	-		-
1S2251	Si-Di	=1S2247:1200V	-		-
1S2252	Si-Di	=1S2247:1500V	-		-
1S2253	Si-Di	=1S2247:2000V	-		-
1S2254	Si-Di	=1S2247:2500V	-		-
1S2255	Si-Di	=1S2247:3000V	-		-
1S2256	Si-Di	Gl-L,1200V,250A(Tc=111o)	-	Mit	-
1S2257	Si-Di	=1S2256:1500V	-		-
1S2258	Si-Di	=1S2256:1600V	-		-
1S2259	Si-Di	=1S2256:1800V	-		-
1S226	Z-Di	=1S220:11V	34a$	-	-
1S2260	Si-Di	=1S2256:2000V	-		-
1S2261	Si-Di	Gl-L,1200V,800A(Tc=101o)	-	Mit	-
1S2262	Si-Di	=1S2261:1600V	-		-
1S2263	Si-Di	=1S2261:1800V	-		-
1S2264	Si-Di	=1S2261:2000V	-		-
1S2265	Si-Di	=1S2261:2500V	-		-
1S2266	Si-Di	=1S2261:2800V	-		-
1S2267	C-Di	VHF-AFC,25V,10o16/3,5o6pF(2/10V)	31a	Hit	BA125,BB119,1SV114,1SV125
1S2268	C-Di	UHF-AFC,25V,10o16/3,5o6pF(2/10V)	31a	Hit	BA121,BB117,BB417,1SV89
1S2269	Si-Di	Gl,Uni,400V,1A	31a	Sak	BY126..127,BY133..134,1N4004..07,+
1S227	Z-Di	=1S220:12V	34a$	-	-
1S2270	Si-Di	-	31a	Sanken	BY226..227,BY251..255,1N5393..99..
1S2270(A)	Z-Di	=1S2030[TexμS]:27V	31a	Tix	→1S2030
1S2270(A)[Texas]	Z-Di	=1S2030[Texas]:27V	31a	Tix	→1S2030
1S2270[Sanken]	Si-Di	Gl,Uni,200V,1,3A	31a	Sak	BY226..227,BY251..255,1N5393..99,+
1S2271	Si-Di	-	31a	Sanken	BY226..227,BY252..255,1N5395..99..
1S2271[Sanken]	Si-Di	=1S2270:400V	31a	-	BY226..227,BY252..255,1N5395..99,+
1S2272	Si-Di	-	31a	Sanken	BY226..227,BY253..255,1N5397..99..
1S2272[Sanken]	Si-Di	=1S2270:600V	31a	-	BY226..227,BY253..255,1N5397..99,+
1S2273	Si-Di	-	31a	Sanken	BY227,BY254..255,1N5398..99..
1S2273[Sanken]	Si-Di	=1S2270:800V	31a	-	BY227,BY254..255,1N5398..99,+
1S2274	Si-Di	-	31a	Sanken	BY227,BY255,BYX86,1N5399..
1S2274[Sanken]	Si-Di	=1S2270:1000V	31a	-	BY227,BY255,BYX86,1N5399,+
1S2277	Si-Di	Gl,S,200V,0,3A,<800ns	31a	Sak	BA157..159,BY204/4,BY206..207,+
1S2278	Si-Di	=1S2277:400V	31a	-	BA157..159,BY204/4,BY207,+
1S2279	Si-Di	=1S2277:600V	31a	-	BA158..159,BY204/8,BY207,+
1S228	Z-Di	=1S220:13V	34a$	-	-
1S2280	Si-Di	=1S2277:800V	31a	-	BA159,BY204/8,BY208/800,+
1S2281	Si-Di	=1S2277:1000V	31a	-	BA159,BY204/10,BY208/1000,+
1S2282(A)	Z-Di	2,5..3,5V,10W(Tc=115°)	32b&	Hit	BZX98/..BZY93/..ZX..1N2970..89
1S2282(A)[Hit.]	Z-Di	2,5..3,5V,10W(Tc=115o)	32b&	Hit	BZX98/..,BZY93/..,ZX..,1N2970..89

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1S2283(A)	Z-Di	=1S2282:3,4..4,6V	32b&	Hit	-
1S2283(A)[Hit.]	Z-Di	=1S2282:3,4..4,6V	32b&	-	-
1S2284(A	Z-Di	=1S2282:4,4..5,4V	32b&	Hit	-
1S2284(A)	Z-Di	=1S2282:4,4..5,4V	32b&	Hit	-
1S2284(A)[Hit.]	Z-Di	=1S2282:4,4..5,4V	32b&	-	-
1S2285(A)	Z-Di	=1S2282:5,2..6,8V	32b&	Hit	-
1S2285(A)[Hit.]	Z-Di	=1S2282:5,2..6,8V	32b&	-	-
1S2286(A)	Z-Di	=1S2282:6,2..7,9V	32b&	Hit	-
1S2286(A)[Hit.]	Z-Di	=1S2282:6,2..7,9V	32b&	-	-
1S2287(A)	Z-Di	=1S2282:7,7..8,7V	32b&	Hit	-
1S2287(A)[Hit.]	Z-Di	=1S2282:7,7..8,7V	32b&	-	-
1S2288(A)	Z-Di	=1S2282:8,5..9,6V	32b&	Hit	-
1S2288(A)[Hit.]	Z-Di	=1S2282:8,5..9,6V	32b&	-	-
1S2289(A)	Z-Di	=1S2282:9,4..10,6V	32b&	Hit	-
1S2289(A)[Hit.]	Z-Di	=1S2282:9,4..10,6V	32b&	-	-
1S229	Z-Di	=1S220:14V	34a$	-	-
1S2290(A)	Z-Di	=1S2282:10,4..11,6V	32b&	Hit	-
1S2290(A)[Hit.]	Z-Di	=1S2282:10,4..11,6V	32b&	-	-
1S2291(A)	Z-Di	=1S2282:11,4..12,7V	32b&	Hit	-
1S2291(A)[Hit.]	Z-Di	=1S2282:11,4..12,7V	32b&	-	-
1S2292(A)	Z-Di	=1S2282:12,4..14,1V	32b&	Hit	-
1S2292(A)[Hit.]	Z-Di	=1S2282:12,4..14,1V	32b&	-	-
1S2293(A)	Z-Di	=1S2282:13,5..15,6V	32b&	Hit	-
1S2293(A)[Hit.]	Z-Di	=1S2282:13,5..15,6V	32b&	-	-
1S2294(A)	Z-Di	=1S2282:15,3..17,1V	32b&	Hit	-
1S2294(A)[Hit.]	Z-Di	=1S2282:15,3..17,1V	32b&	-	-
1S2295(A	Z-Di	=1S2282:16,8..19,1V	32b&	Hit	-
1S2295(A)	Z-Di	=1S2282:16,8..19,1V	32b&	Hit	-
1S2295(A)[Hit.]	Z-Di	=1S2282:16,8..19,1V	32b&	-	-
1S2296(A)	Z-Di	=1S2282:18,8..21,2V	32b&	Hit	-
1S2296(A)[Hit.]	Z-Di	=1S2282:18,8..21,2V	32b&	-	-
1S2297(A)	Z-Di	=1S2282:20,8..23,3V	32b&	Hit	-
1S2297(A)[Hit.]	Z-Di	=1S2282:20,8..23,3V	32b&	-	-
1S2298(A)	Z-Di	=1S2282:22,7..25,6V	32b&	Hit	-
1S2298(A)[Hit.]	Z-Di	=1S2282:22,7..25,6V	32b&	-	-
1S2299(A)	Z-Di	=1S2282:25,1..28,9V	32b&	Hit	-
1S2299(A)[Hit.]	Z-Di	=1S2282:25,1..28,9V	32b&	-	-
1S23	Ge-Di	=1S22:300V	-	Tos	-
1S230	Z-Di	=1S220:15V	34a$	-	-
1S2300(A)	Z-Di	=1S2030[Texas]:30V	31a	Tix	→1S2030
1S2300(A)	Z-Di	=1S2282:28..32V	32b&	Hit	-
1S2300(A)[Hit.]	Z-Di	=1S2282:28..32V	32b&	-	-
1S2300(A)[Texas]	Z-Di	=1S2030[Texas]:30V	31a	Tix	→1S2030
1S2301	Z-Di	1,4..2,6V,1W	31a	Hit	BZW22/..,BZX61/..,ZPY..,1N5913..18,+
1S2302	Z-Di	=1S2301:2,4..3,6V	31a	-	-
1S2303	Z-Di	=1S2301:3,4..4,6V	31a	-	-
1S2304	Z-Di	=1S2301:4,4..5,4V	31a	-	-
1S2305	Diac	Ub=28..38V,Ib<0,2mA,Itsm=2A	31l	Hit	1N5761,N413M,D3202Y,BR100,DO201YR
1S2306	Si-Di	Gl,Uni,600V,1A	34b&	Tos	BY126..127,BY133..134,1N4005..07,+
1S2307	Si-Di	=1S2306:800V	34b&	-	BY127,BY133,BY228,1N4006..07,+
1S2308	Si-Di	=1S2306:1000V	34b&	-	BY127,BY133,BY228,1N4007,+
1S2309	Si-Di	=1S2306:1500V	34b&	-	BY228,BY400,BY448,EM516,GP10W
1S231	Z-Di	=1S220:16V	34a$	-	-
1S2310	Si-Di	Gl,Uni,600V,0,3A	31a	Tos	BA158..159,BY204/8,BY208/600,+
1S2311	Si-Di	=1S2310:800V	31a	-	BA159,BY204/8,BY208/800,+
1S2312	Si-Di	=1S2310:1000V	31a	-	BA159,BY204/10,BY208/1000,+
1S2313	Si-Di	Gl,Uni,600V,0,15A	31a	Tos	BA158..159,BY204/8,BY208/600,+
1S2314	Si-Di	=1S2313:800V	31a	-	BA159,BY204/8,BY208/800,+
1S2315	Si-Di	=1S2313:1000V	31a	-	BA159,BY204/10,BY208/1000,+
1S2316	Si-Di	Gl,S,400V,0,13A,<300ns	31a	Sak	BA157..159,BY204/4,BY208/600,+
1S2317	Si-Di	=1S2316:600V	31a	-	BA158..159,BY204/8,BY208/800,+
1S2318	Si-Di	=1S2316:800V	31a	-	BA159,BY204/8,BY208/800,+
1S2319	Si-Di	=1S2316:1000V	31a	-	BA159,BY204/10,BY208/1000,+
1S232	Z-Di	=1S220:17V	34a$	-	-

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1S2320	Si-Di	Gl,S,300V,5A,<300ns	-	Sak	(BY229/400,BY233/400,BY277/600,++)
1S2321	Si-Di	Gl,S,400V,1,5A,<300ns	-	Sak	(BY229/400,BY233/400,BY277/600,++)
1S2323	Si-Di	Gl,S,800V,0,4A,<800ns	31a	Hit	BA159,BY204/8,BY208/800,BY228,+
1S2324	Si-Di	=1S2323:1000V	31a	-	BA159,BY204/10,BY208/1000,BY228+
1S2325	Si-Di	=1S2323:1300V	31a	-	BY228,BY268..269,BY400,BY448
1S2326	Si-Di	=1S2323:1500V	31a	-	BY228,BY269,BY400,BY448
1S2329	Si-Di	Gl,Uni,400V,0,3A	31a	Tos	BA147..159,BY204/4,BY207,+
1S233	Z-Di	=1S220:18V	34a$	-	-
1S2330(A)	Z-Di	=1S2030[Texas]:33V	31a	Tix	→1S2030
1S2330(A)[Texas]	Z-Di	=1S2030[Texas]:33V	31a	Tix	→1S2030
1S2331	Si-Di	Gl-L,100V,100A(Tc=130o)	73b	Org	D120/400,DS80-04A,DS85-01C
1S2332	Si-Di	=1S2331:200V	73b	-	D120/400,DS80-04A,DS85-02C
1S2333	Si-Di	=1S2331:300V	73b	-	D120/400,DS80-04A,DS85-04C
1S2334	Si-Di	=1S2331:400V	73b	-	D120/400,DS80-04A,DS85-04C
1S2335	Si-Di	=1S2331:600V	73b	-	D120/800,DS80-07A,DS85-06C
1S2336	Si-Di	=1S2331:800V	73b	-	D120/800,DS80-11A,DS85-08C
1S2337	Si-Di	=1S2331:1000V	73b	-	D120/1200,DS80-14A,DS85-10C
1S2339	C-Di	VHF-Tuning/AFC,20V,3,5o5,5pF(10V)	31a	Njr	BB105,BB205,BB305,BB405,BB505+
1S234	Z-Di	=1S220:19V	34a$	-	-
1S2340	C-Di	AFC,25V,7<10pF(6V)	7a	Tos	BA121,BA125,BB117,BB119,+
1S2348H	Si-Di	SS,65V,0,25A,<8ns	31a	Hit	BAW62,BAX95,1N4446..48,1N4148..49+
1S2349	Si-Di	Dual,Gl,200V,1,8A	12p	Shi	2x(BY226..227,BY251..255,1N5060,++)
1S2349R..2350R..	Si-Di	=1S2349:	12q	-	2x(BY226..227,BY251..255,1N5060,++)
1S2349R..2350R...	Si-Di	-	12q	-	2X(BY226..227,BY251..255,1N5060..)
1S235	Z-Di	=1S220:20V	34a$	-	-
1S2350	Si-Di	=1S2349:400V	12p	-	2x(BY226..227,BY252..255,1N5060,++)
1S2351	Si-Di	Gl,S,200V,0,1A,<1,5?s	31a	Shi	BA157..159,BAY88..91,BY203/12,+
1S2352	Si-Di	=1S2351:600V	31a	-	BA158..159,BAY89..91,BY203/12,+
1S2353	Si-Di	=1S2351:800V	31a	-	BA159,BAY90..91,BY203/12,+
1S2354	Si-Di	=1S2351:1000V	31a	-	BA159,BAY90..91,BY203/12,+
1S2355	Si-Di	=1S2351:1500V	31a	-	BAY91,BY203/16,BYS84,SHG1,5,+
1S2356	Si-Di	Gl,contr.av.,200V,0,4A	31a	Shi	BYW52..56,1N4245..4249
1S2357	Si-Di	=1S2356:400V	31a	-	BYW53..56,1N4246..4249
1S2358	Si-Di	Gl,contr.av.,200V,0,6A	31a	Shi	BYW52..56,1N4245..4249
1S2359	Si-Di	=1S2358:400V	31a	-	BYW53..56,1N4246..4249
1S236	Z-Di	=1S220:22V	34a$	-	-
1S2361	Si-Di	Gl,Uni,200V,1A	31a	Shi	BY126..127,BY133..134,1N4003..07,+
1S2362	Si-Di	=1S2361:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S2363	Si-Di	=1S2361:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S2364	Si-Di	=1S2361:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S2365	Si-Di	=1S2361:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S2366	Si-Di	Gl,S,200V,0,1A,<1,5?s	31a	Shi	BA157..159,BAY88..91,BY203/12,+
1S2367	Si-Di	=1S2366:600V	31a	-	BA158..159,BAY89..91,BY203/12,+
1S2368	Si-Di	=1S2366:800V	31a	-	BA159,BAY90..91,BY203/12,+
1S2369	Si-Di	=1S2368:1000V	31a	-	BA159,BAY90..91,BY203/12,+
1S237	Z-Di	=1S220:24V	34a$	-	-
1S2370	Si-Di	=1S2366:1500V	31a	-	BAY91,BY203/12,BYS84,SHG1,5,+
1S2371(A)	Si-Br	Gl-Br,100V,1A	-	Shi	B250C1500
1S2372(A)	Si-Br	=1S2371:200V	-		B250C1500
1S2373(A)	Si-Br	=1S2371:400V	-		B250C1500
1S2374(A)	Si-Br	=1S2371:600V	-		B250C1500
1S2375(A)	Si-Br	=1S2371:contr.av.,200V	-		-
1S2376(A)	Si-Br	=1S2371:contr.av.,400V	-		-
1S2377	Si-Di	Dual,Gl,100V,1,8A	12p	Shi	2x(BY226..227,BY251..255,1N5060,++)
1S2377R...2380R..	Si-Di	=1S2377:	12q	-	2x(BY226..227,BY251..255,1N5061,++)
1S2377R..2380R...	Si-Di	-	12q	-	2X(BY226..227,BY251..255,1N5061..)
1S2378	Si-Di	=1S2377:200V	12p	-	2x(BY226..227,BY251..255,1N5060,++)
1S2379	Si-Di	=1S2377:400V	12p	-	2x(BY226..227,BY252..255,1N5060,++)
1S238	Z-Di	=1S220:25V	34a$	-	-
1S2380	Si-Di	=1S2377:600V	12p	-	2x(BY226..227,BY253..255,1N5061,++)
1S2381	Si-Di	Dual,Gl,100V,1A	12p	Shi	2x(BY126..127,BY133..135,1N4002,++)
1S2382	Si-Di	=1S2381:200V	12p	-	2x(BY126..127,BY133..134,1N4003,++)
1S2383	Si-Di	=1S2381:400V	12p	-	2x(BY126..127,BY133..134,1N4004,++)
1S2384	Si-Di	=1S2381:600V	12p	-	2x(BY126..127,BY133..134,1N4005,++)

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1S2387H	Si-Di	SS,130V,0,25A,<10ns	31a	Hit	BA203,BAV14
1S239	Z-Di	=1S220:27V	34a$	-	-
1S2390	Si-Di	GI,Uni,50V,1A	31a	Nec	BY126..127,BY133..135,1N4001..07,+
1S2391	Si-Di	=1S2390:100V	31a	-	BY126..127,BY133..135,1N4002..07,+
1S2392	Si-Di	=1S2390:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S2393	Si-Di	=1S2390:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S2394	Si-Di	=1S2390:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S2395	Si-Di	=1S2390:500V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S2396	Si-Di	=1S2390:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S2397	Si-Di	=1S2390:700V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S2398	Si-Di	=1S2390:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S2399	Si-Di	=1S2390:900V	31a	-	BY127,BY133,BY227,1N4007,+
1S24	Ge-Di	=1S22:200V	-	Tos	-
1S240	Z-Di	=1S220:30V	34a$	-	-
1S2400	Si-Di	=1S2390:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S2401	Si-Di	GI,Uni,100V,1A	31a	Mit	BY126..127,BY133..135,1N4002..07,+
1S2402	Si-Di	=1S2401:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S2403	Si-Di	=1S2401:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S2404	Si-Di	=1S2401:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S2405	Si-Di	=1S2401:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S2406	Si-Di	=1S2401:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S2407	Si-Di	=1S2401:1200V	31a	-	BY127,BY133,BY227,GP10Q,+
1S2408	Si-Di	GI,Uni,50V,2A	31a	Mit	BY226..227,BY251..255,1N5060..62,+
1S2409	Si-Di	=1S2408:100V	31a	-	BY226..227,BY251..255,1N5060..62,+
1S241	Z-Di	=1S220:33V	34a$	-	-
1S2410	Si-Di	=1S2408:200V	31a	-	BY226..227,BY251..255,1N5060..62,+
1S2411	Si-Di	=1S2408:300V	31a	-	BY226..227,BY252..255,1N5060..62,+
1S2412	Si-Di	=1S2408:400V	31a	-	BY226..227,BY252..255,1N5060..62,+
1S2413	Si-Di	=1S2408:500V	31a	-	BY226..227,BY253..255,1N5061..62,+
1S2414	Si-Di	=1S2408:600V	31a	-	BY226..227,BY253..255,1N5061..62,+
1S2415	Si-Di	GI,Uni,50V,2A	31a	Mit	BY226..227,BY251..255,1N5060..62,+
1S2416	Si-Di	=1S2415:100V	31a	-	BY226..227,BY251..255,1N5060..62,+
1S2417	Si-Di	=1S2415:200V	31a	-	BY226..227,BY251..255,1N5060..62,+
1S2418	Si-Di	=1S2415:300V	31a	-	BY226..227,BY252..255,1N5060..62,+
1S2419	Si-Di	=1S2415:400V	31a	-	BY226..227,BY252..255,1N5060..62,+
1S242	Z-Di	=1S220:36V	34a$	-	-
1S2420	Si-Di	=1S2415:500V	31a	-	BY226..227,BY253..255,1N5061..62,+
1S2421	Si-Di	=1S2415:600V	31a	-	BY226..227,BY253..255,1N5061..62,+
1S2422	Si-Di	GI-L,50V,20A(Tc=115o)	75a$	Mit	1N3491..3495
1S2422R...2427R..	Si-Di	=1S2422:	75b&	-	DS25-...A
1S2422R..2427R...	Si-Di	-	75b&	-	DS25-..A
1S2423	Si-Di	=1S2422:100V	75a$	-	1N3492..3495
1S2424	Si-Di	=1S2422:200V	75a$	-	1N3493..3495
1S2425	Si-Di	=1S2422:300V	75a$	-	1N3494..3495
1S2426	Si-Di	=1S2422:400V	75a$	-	1N3495
1S2427	Si-Di	=1S2422:500V	75a$	-	-
1S2428(R)	Si-Di	GI-L,50V,15A(Tc=115o)	-	Mit	-
1S2429(R)	Si-Di	=1S2428:100V	-		-
1S243	Z-Di	=1S220:39V	34a$	-	-
1S2430(R)	Si-Di	=1S2428:200V	-		-
1S2431(R)	Si-Di	=1S2428:300V	-		-
1S2432(R)	Si-Di	=1S2428:400V	-		-
1S2433(R)	Si-Di	=1S2428:500V	-		-
1S2434	Si-Di	GI-L,50V,12A(Tc=120o)	32a$	Mit	1N3765..3768,1N4525..4530
1S2434R...2439R..	Si-Di	=1S2434:	32b&	-	D24/..C,1N3765R..3768R
1S2434R..2439R...	Si-Di	-	32b&	-	D24/..C,1N3765R..3768R
1S2435	Si-Di	=1S2434:100V	32a$	-	1N3765..3768,1N4525..4530
1S2436	Si-Di	=1S2434:200V	32a$	-	1N3765..3768,1N4525..4530
1S2437	Si-Di	=1S2434:300V	32a$	-	1N3765..3768,1N4526..4530
1S2438	Si-Di	=1S2434:400V	32a$	-	1N3765..3768,1N4526..4530
1S2439	Si-Di	=1S2434:500V	32a$	-	1N3765..3768,1N4527..4530
1S244	Z-Di	=1S220:43V	34a$	-	-
1S2440	Si-Di	GI-L,50V,25A(Tc=120o)	75a$	Mit	1N3491..3495
1S2440R...244SR..	Si-Di	=1S2440:	75b&	-	DS25-..A

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1S2440R..2445R...	Si-Di	-	75b&	-	D525-..A
1S2441	Si-Di	=1S2440:100V	75a$	-	1N3492..3495
1S2442	Si-Di	=1S2440:200V	75a$	-	1N3493..3495
1S2443	Si-Di	=1S2440:300V	75a$	-	1N3494..3495
1S2444	Si-Di	=1S2440:400V	75a$	-	1N3495
1S2445	Si-Di	=1S2440:500V	75a$	-	-
1S2445R...2451R..	Si-Di	=1S2446:	32b&	-	D24/..C, 1N3765R..3768R
1S2445R..2451R...	Si-Di	-	32b&	-	D24/..C, 1N3765R..3768R
1S2446	Si-Di	Gl-L, 50V, 25A(Tc=120o)	32a$	Mit	1N3765..3768, 1N4525..4530
1S2447	Si-Di	=1S2446:100V	32a$	-	1N3765..3768, 1N4525..4530
1S2448	Si-Di	=1S2446:200V	32a$	-	1N3765..3768, 1N4525..4530
1S2449	Si-Di	=1S2446:300V	32a$	-	1N3765..3768, 1N4526..4530
1S245	Z-Di	=1S220:45V	34a$	-	-
1S2450	Si-Di	=1S2446:400V	32a$	-	1N3765..3768, 1N4526..4530
1S2451	Si-Di	=1S2446:500V	32a$	-	1N3765..3768, 1N4527..4530
1S2452	Ref-Di	6..7V, 0,25W	2c	Tos	BZV10, BZV27, 1N4580
1S2453	Ref-Di	6..7V, 0,25W	2c	-	BZV11, BZV28, 1N4581
1S2454	Ref-Di	6..7V, 0,25W	2c	-	BZV12, BZV29, 1N4582
1S2455	Si-Di	Gl, Uni, 100V, 2,5A	31a	Hit	BY251..255, BY259/150, 1N5402..08, +
1S2456	Si-Di	=1S2455:200V	31a	-	BY251..255, BY259/300, 1N5402..08, +
1S2457	Si-Di	=1S2455:400V	31a	-	BY252..255, BY259/600, 1N5404..08, +
1S2458	Si-Di	=1S2455:600V	31a	-	BY253..255, BY259/600, 1N5406..08, +
1S2459	Si-Di	=1S2455:800V	31a	-	BY254..255, BY259/900, 1N5407..08, +
1S246	Z-Di	=1S220:47V	34a$	-	-
1S2460	Si-Di	Dem, Uni, 70V, 0,1A	31a	Tos	BA147/100, BAY19..21, 1N5606..09, +
1S2461	Si-Di	=1S2460:120V	31a	-	BA147/150, BAY20..21, 1N5606..09, +
1S2462	Si-Di	=1S2460:220V	31a	-	BA147/230, BAY21, BAY46, BAY88, +
1S2463	Si-Di	=1S2460:320V	31a	-	BA147/300, BAY21, BAY46, BAY88, +
1S2464(R)	Si-Di	Gl-L, 200V, 15A(Tc=120o)	-	Sak	-
1S2468	Si-Di	kV-Gl, 36kV, 0,02A	-	Sak	-
1S2469	Si-Di	kV-Gl, 18kV, 0,02A	?31a	Sak	CY20, HS13
1S247	Z-Di	=1S220:50V	34a$	-	-
1S2470	Si-Di	=1S2469:12kV	?31a	-	HS10
1S2471	Si-Di	SS, 90V, 0,13A, <4ns	31a	Rhm	BA219, 1N4148..49, 1N4446..4449, +
1S2472	Si-Di	SS, 55V, 0,12A, <4ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49+
1S2473	Si-Di	SS, 40V, 0,11A, <4ns	31a	Rhm	BAW62, BAX95, 1N4148..49, 1N4446..49+
1S2474	Z-Di	0,6..0,8V, 0,75W	2d	Stl	BZW22/.., BZX61/.., ZPY.., 1N5913..56, +
1S2474R...2530R..	Z-Di	=1S2474..2530:	2c	-	-
1S2474R..2530R...	Z-Di	=1S2474..2530:	2c	-	-
1S2475	Z-Di	=1S2474:1,3..1,7V	2d	-	-
1S2476	Z-Di	=1S2474:1,69..1,9V	2d	-	-
1S2477	Z-Di	=1S2474:1,88..2,1V	2d	-	-
1S2478	Z-Di	=1S2474:2,09..2,31V	2d	-	-
1S2479	Z-Di	=1S2474:2,28..2,55V	2d	-	-
1S248	Z-Di	=1S220:52V	34a$	-	-
1S2480	Z-Di	=1S2474:2,54..2,85V	2d	-	-
1S2481	Z-Di	=1S2474:2,83..3,15V	2d	-	-
1S2482	Z-Di	=1S2474:3,13..3,47V	2d	-	-
1S2483	Z-Di	=1S2474:3,42..3,78V	2d	-	-
1S2484	Z-Di	=1S2474:3,7..4,1V	2d	-	-
1S2485	Z-Di	=1S2474:4,08..4,52V	2d	-	-
1S2486	Z-Di	=1S2474:4,47..4,94V	2d	-	-
1S2487	Z-Di	=1S2474:4,84..5,36V	2d	-	-
1S2488	Z-Di	=1S2474:5,32..5,9V	2d	-	-
1S2489	Z-Di	=1S2474:5,89..6,51V	2d	-	-
1S249	Z-Di	=1S220:56V	34a$	-	-
1S2490	Z-Di	=1S2474:6,46..7,14V	2d	-	-
1S2491	Z-Di	=1S2474:7,12..7,88V	2d	-	-
1S2492	Z-Di	=1S2474:7,79..8,63V	2d	-	-
1S2493	Z-Di	=1S2474:8,62..9,56V	2d	-	-
1S2494	Z-Di	=1S2474:9,5..10,5V	2d	-	-
1S2495	Z-Di	=1S2474:10,4..11,6V	2d	-	-
1S2496	Z-Di	=1S2474:11,4..12,6V	2d	-	-
1S2497	Z-Di	=1S2474:12,3..13,7V	2d	-	-

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1S2498	Z-Di	=1S2474:13,2..15,8V	2d	-	-
1S2499	Z-Di	=1S2474:15,2..17V	2d	-	-
1S25	Ge-Di	=1S22:100V	-	Tos	-
1S250	Z-Di	=1S220:62V	34a$	-	-
1S2500	Z-Di	=1S2474:16,9..19V	2d	-	-
1S2501	Z-Di	=1S2474:18,8..21V	2d	-	-
1S2502	Z-Di	=1S2474:20,9..23,1V	2d	-	-
1S2503	Z-Di	=1S2474:22,8..25,5V	2d	-	-
1S2504	Z-Di	=1S2474:25,4..28,5V	2d	-	-
1S2505	Z-Di	=1S2474:28,3..31,5V	2d	-	-
1S2506	Z-Di	=1S2474:31,3..34,7V	2d	-	-
1S2507	Z-Di	=1S2474:34,2..37,8V	2d	-	-
1S2508	Z-Di	=1S2474:37..41V	2d	-	-
1S2509	Z-Di	=1S2474:40,8..45,2V	2d	-	-
1S251	Z-Di	=1S220:68V	34a$	-	-
1S2510	Z-Di	=1S2474:44,7..49,4V	2d	-	-
1S2511	Z-Di	=1S2474:48,4..53,6V	2d	-	-
1S2512	Z-Di	=1S2474:53,2..59V	2d	-	-
1S2513	Z-Di	=1S2474:58,9..65,1V	2d	-	-
1S2514	Z-Di	=1S2474:64,6..71,4V	2d	-	-
1S2515	Z-Di	=1S2474:71,2..78,8V	2d	-	-
1S2516	Z-Di	=1S2474:77,9..86,3V	2d	-	-
1S2517	Z-Di	=1S2474:86,2..95,6V	2d	-	-
1S2518	Z-Di	=1S2474:95..105V	2d	-	-
1S2519	Z-Di	=1S2474:104..116V	2d	-	-
1S252	Z-Di	=1S220:75V	34a$	-	-
1S2520	Z-Di	=1S2474:114..126V	2d	-	-
1S2521	Z-Di	=1S2474:123..137V	2d	-	-
1S2522	Z-Di	=1S2474:132..158V	2d	-	-
1S2523	Z-Di	=1S2474:152..170V	2d	-	-
1S2524	Z-Di	=1S2474:169..190V	2d	-	-
1S2525	Z-Di	=1S2474:188..210V	2d	-	-
1S2526	Z-Di	=1S2474:209..231V	2d	-	-
1S2527	Z-Di	=1S2474:228..255V	2d	-	-
1S2528	Z-Di	=1S2474:254..285V	2d	-	-
1S2529	Z-Di	=1S2474:283..315V	2d	-	-
1S253	Z-Di	=1S220:82V	34a$	-	-
1S2530	Z-Di	=1S2474:313..347V	2d	-	-
1S2531	Z-Di	0,6..0,8V,0,25W	2d	Stl	BZX55/..,BZX79/..,ZPD..,1N5221..71,+
1S2531R...2575R..	Z-Di	=1S2531:	2c	-	-
1S2531R..2575R...	Z-Di	=1S2531:	2c	-	-
1S2532	Z-Di	=1S2531:1,3..1,7V	2d	-	-
1S2533	Z-Di	=1S2531:1,69..1,9V	2d	-	-
1S2534	Z-Di	=1S2531:1,88..2,1V	2d	-	-
1S2535	Z-Di	=1S2531:2,09..2,31V	2d	-	-
1S2536	Z-Di	=1S2531:2,28..2,55V	2d	-	-
1S2537	Z-Di	=1S2531:2,54..2,85V	2d	-	-
1S2538	Z-Di	=1S2531:2,83..3,15V	2d	-	-
1S2539	Z-Di	=1S2531:3,13..3,47V	2d	-	-
1S254	Z-Di	=1S220:91V	34a$	-	-
1S2540	Z-Di	=1S2531:3,42..3,78V	2d	-	-
1S2541	Z-Di	=1S2531:3,7..4,1V	2d	-	-
1S2542	Z-Di	=1S2531:4,08..4,52V	2d	-	-
1S2543	Z-Di	=1S2531:4,47..4,94V	2d	-	-
1S2544	Z-Di	=1S2531:4,84..5,36V	2d	-	-
1S2545	Z-Di	=1S2531:5,32..5,9V	2d	-	-
1S2546	Z-Di	=1S2531:5,89..6,51V	2d	-	-
1S2547	Z-Di	=1S2531:6,46..7,14V	2d	-	-
1S2548	Z-Di	=1S2531:7,12..7,88V	2d	-	-
1S2549	Z-Di	=1S2531:7,79..8,63V	2d	-	-
1S255	Z-Di	=1S220:100V	34a$	-	-
1S2550	Z-Di	=1S2531:8,62..9,56V	2d	-	-
1S2551	Z-Di	=1S2531:9,5..10,5V	2d	-	-
1S2552	Z-Di	=1S2531:10,4..11,6V	2d	-	-

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1S2553	Z-Di	=1S2531:11,4..12,6V	2d	-	-
1S2554	Z-Di	=1S2531:12,3..13,7V	2d	-	-
1S2555	Z-Di	=1S2531:13,2..15,8V	2d	-	-
1S2556	Z-Di	=1S2531:15,2..17V	2d	-	-
1S2557	Z-Di	=1S2531:16,9..19V	2d	-	-
1S2558	Z-Di	=1S2531:18,8..21V	2d	-	-
1S2559	Z-Di	=1S2531:20,9..23,1V	2d	-	-
1S256	Z-Di	=1S220:105V	34a$	-	-
1S2560	Z-Di	=1S2531:22,8..25,5V	2d	-	-
1S2561	Z-Di	=1S2531:25,4..28,5V	2d	-	-
1S2562	Z-Di	=1S2531:28,3..31,5V	2d	-	-
1S2563	Z-Di	=1S2531:31,3..34,7V	2d	-	-
1S2564	Z-Di	=1S2531:34,2..37,8V	2d	-	-
1S2565	Z-Di	=1S2531:37..41V	2d	-	-
1S2566	Z-Di	=1S2531:40,8..45,2V	2d	-	-
1S2567	Z-Di	=1S2531:44,7..49,4V	2d	-	-
1S2568	Z-Di	=1S2531:48,4..53,6V	2d	-	-
1S2569	Z-Di	=1S2531:53,2..59V	2d	-	-
1S257	Z-Di	=1S220:110V	34a$	-	-
1S2570	Z-Di	=1S2531:58,9..65,1V	2d	-	-
1S2571	Z-Di	=1S2531:64,6..71,4V	2d	-	-
1S2572	Z-Di	=1S2531:71,2..78,8V	2d	-	-
1S2573	Z-Di	=1S2531:77,9..86,3V	2d	-	-
1S2574	Z-Di	=1S2531:86,2..95,6V	2d	-	-
1S2575	Z-Di	=1S2531:95..105V	2d	-	-
1S258	Z-Di	=1S220:120V	34a$	-	-
1S2588	C-Di	VHF-Band-5,30V,<2pF(15V),<0,6e	31a	Njr	BA182,BA243,BA283,BA483..484,+
1S2589	Si-Di	Uni,50V,0,75A	31a	Hit	BY126..127,BY133..135,1N4001..07,+
1S259	Z-Di	=1S220:130V	34a$	-	-
1S2590	Si-Di	=1S2589:100V	31a	-	BY126..127,BY133..135,1N4002..07,+
1S2591	Si-Di	=1S2589:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S2592	Si-Di	Gl,S,800V,1A,<800ns	31a	Hit	BY231/800,BY400,MR817,RGP10K,+
1S2593	Si-Di	=1S2592:1000V	31a	-	BY231/1000,BY400,MR818,RGP10M,+
1S2594	Si-Di	=1S2592:1300V	31a	-	BY231/1400,BY228,BY400,BY448
1S2595	Si-Di	=1S2592:1500V	31a	-	BY231/1500,BY228,BY400,BY448
1S2596	Si-Di	Gl,S,200V,2A,<600ns	31a	Hit	BY218/200,BY296..299,BYW32..36,+
1S2597	Si-Di	=1S2596:400V	31a	-	BY218/400,BY298..299,BYW34..36,+
1S2598	Si-Di	=1S2596:600V	31a	-	BY218/600,BY228,BY299,BYW36,+
1S26	Ge-Di	Gl-L,100V,3,5A	?34a$	Njr	-
1S260	Z-Di	=1S220:140V	34a$	-	-
1S2602	Si-Di	Gl,contr.av.,200V,1A	31a	Nec	BYW52..56,1N4245..49,1N5060..62
1S2603	Si-Di	=1S2602:300V	31a	-	BYW53..56,1N4246..49,1N5060..62
1S2604	Si-Di	=1S2602:400V	31a	-	BYW53..56,1N4246..49,1N5060..62
1S2605	Si-Di	=1S2602:500V	31a	-	BYW54..56,1N4247..49,1N5061..62
1S2606	Si-Di	=1S2602:600V	31a	-	BYW54..56,1N4247..49,1N5061..62
1S2607	Si-Di	=1S2602:700V	31a	-	BYW55..56,1N4248..49,1N5062
1S2608	Si-Di	=1S2602:800V	31a	-	BYW55..56,1N4248..49,1N5062
1S2609	Si-Di	=1S2602:900V	31a	-	BYW56,1N4249
1S261	Z-Di	=1S220:150V	34a$	-	-
1S2610	Si-Di	=1S2602:1000V	31a	-	BYW56,1N4249
1S2611	Si-Di	=1S2602:1100V	31a	-	SSiB9860A
1S2612	Si-Di	=1S2602:1200V	31a	-	SSiB9880A
1S2613	Si-Di	=1S2602:1300V	31a	-	SSiB9880A
1S2614	Si-Di	=1S2602:1400V	31a	-	SSiB9880A
1S2615	Si-Di	Gl,S,600V,1A,<250ns	34b&	Tos	BY201/6,BYV14..16,BYX55/600,+
1S2616	Si-Di	=1S2615:<350ns	34b&	-	BY201/6,BYV14..16,BYX55/600,+
1S2617	Si-Di	=1S2615:<900ns	34b&	-	BY201/6,BYV14..16,BYX55/600,+
1S2618	Si-Di	Gl,S,800V,1A,<800ns	31a	Hit	BY245/800,BY231/800,MR817,RGP10K,+
1S2619	Si-Di	kV-Gl,8kV,0,04A	31a	Inr	1N5184
1S262	Z-Di	4,5V,10%,10W	32a$	Tos	BZX98/..,BZY93/..,ZL..,1N2970..3011+
1S2620	Si-Di	kV-Gl,16kV,0,04A	31a	Inr	1N3054
1S2621	Si-Di	kV-Gl,24kV,0,04A	31a	Inr	1N3058
1S2622	Si-Di	kV-Gl,32kV,0,04A	31a	Inr	1N3061
1S2628	Si-Di	Gl/S-L,100V,5,5A,<300ns	32b&	Fjd	1N3880R..3883R

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1S2629	Si-Di	=1S2628:200V	32b&	-	1N3881R..3883R
1S263	Z-Di	=1S262:5,5V	32a$	-	-
1S2630	Si-Di	Gl/S-L,100V,8A(Tc=70o),<300ns	32	Fjd	BYV30/100,BYW30/100,BYX61/100,+
1S2631	Si-Di	=1S2630:200V	32	-	BYV30/200,BYW30/200,BYX61/200,+
1S2632	Si-Di	Gl/S-L,100V,16A(Tc=70o),<300ns	73	Fjd	-
1S2633	Si-Di	=1S2632:200V	73	-	-
1S2634	Si-Di	Gl/S-L,100V,46A(Tc=70o),<400ns	73	Fjd	-
1S2635	Si-Di	=1S2634:200V	73	-	-
1S2636	Si-Di	Gl/S-L,100V,95A(Tc=70o),<400ns	73b&	Fjd	-
1S2637	Si-Di	=1S2636:200V	73b&	-	-
1S2638	C-Di	VHF-AFC	31a	Hit	BA125,BB119,1SV114,1SV125
1S2639	Si-Di	Gl-L,1400V,50A(Tc=125o)	73b&	Rhm	-
1S264	Z-Di	=1S262:6,5V	32a$	-	-
1S2640	Si-Di	=1S2639:1600V	73b&	-	-
1S2641	Si-Di	=1S2639:2000V	73b&	-	-
1S2642	Si-Di	=1S2639:2500V	73b&	-	-
1S2643	Si-Di	=1S2639:3000V	73b&	-	-
1S2644	Si-Di	Gl-L,1400V,80A(Tc=115o)	73b&	Rhm	-
1S2645	Si-Di	=1S2644:1600V	73b&	-	-
1S2646	Si-Di	=1S2644:2000V	73b&	-	-
1S2647	Si-Di	=1S2644:2500V	73b&	-	-
1S2648	Si-Di	=1S2644:3000V	73b&	-	-
1S2649	Si-Di	Gl-L,400V,100A(Tc=90o)	73b&	Rhm	1N3291R..3297R
1S265	Z-Di	=1S262:7,5V	32a$	-	-
1S2650	Si-Di	=1S2649:600V	73b&	-	1N3293R..3297R
1S2651	Si-Di	=1S2649:800V	73b&	-	1N3294R..3297R
1S2652	Si-Di	=1S2649:1000V	73b&	-	1N3295R..3297R
1S2653	Si-Di	=1S2649:1200V	73b&	-	1N3296R..3297R
1S2654	Si-Di	Gl-L,600V,210A(Tc=110o)	73b&	Rhm	1N3740R..3744R
1S2655	Si-Di	=1S2654:800V	73b&	-	1N3741R..3744R
1S2656	Si-Di	=1S2654:1000V	73b&	-	1N3742R..3744R
1S2657	Si-Di	=1S2654:1200V	73b&	-	1N3743R..3744R
1S2658	Si-Di	=1S2654:1400V	73b&	-	1N3744R
1S2659	Si-Di	=1S2654:1600V	73b&	-	-
1S266	Z-Di	=1S262:8,5V	32a$	-	-
1S2660	Si-Di	Gl-L,600V,400A(Tc=100o)	73b&	-	-
1S2661	Si-Di	=1S2660:800V	73b&	-	-
1S2662	Si-Di	=1S2660:1000V	73b&	-	-
1S2663	Si-Di	=1S2660:1200V	73b&	-	-
1S2664	Si-Di	=1S2660:1400V	73b&	-	-
1S2665	Si-Di	=1S2660:1600V	73b&	-	-
1S2666	Si-Di	Gl/S-L,100V,80A,<300ns	73b&	Sak	-
1S2667	Si-Di	=1S2666:200V	73b&	-	-
1S2668	Si-Di	=1S2666:250V	73b&	-	-
1S2669	Si-Di	Gl/S-L,100V,8A(Tc=100o),<300ns	-	Sak	-
1S267	Z-Di	=1S262:9,5V	32a$	-	-
1S2670	Si-Di	=1S2669:250V	-		-
1S2671	Si-Di	=1S2669:400V	-		-
1S2672	Si-Di	Gl,S,200V,0,8A,<200ns	31a	-	BY201/2,BYT52D,BYX92/200,RGP10D
1S2673	Si-Di	=1S2672:300V	31a	-	BY201/3,BYT52G,BYX92/300,RGP10G
1S2674	Si-Di	=1S2672:400V	31a	-	BY201/4,BYT52G,BYX92/400,RGP10G
1S2675	Si-Di	=1S2672:500V	31a	-	BY201/5,BYT52J,RGP10J
1S2676	Si-Di	=1S2672:600V	31a	-	BY201/6,BYT52J,RGP10J
1S2677	Si-Di	=1S2672:700V	31a	-	BYT52K,RGP10K
1S2678	Si-Di	=1S2672:800V	31a	-	BYT52K,RGP10K
1S2679	Si-Di	=1S2672:1000V	31a	-	BYT52M,RGP10M
1S268	Z-Di	=1S262:11V	32a$	-	-
1S2685	Si-Di	VHF-Tuning,30V,1,8..2,8pF(25V)	71a(4mm)	Hit	BB105,BB205,BB305,BB405,BB505+
1S2686	Si-Di	AFC,20V,4..14pF(10V)	31a	Njr	-
1S2687	Si-Di	=1S2666:8..18pF(10V)	31a	Njr	-
1S2688	C-Di	=1S2666:14..26pF(10V)	31a	Njr	-
1S2689	Si-Di	=1S2666:15V,22..38pF(10V)	31a	Njr	-
1S269	Z-Di	=1S262:12V	32a$	-	-
1S2692	Si-Di	VHF-Band-S,35V,<1,2pF(6V),<1,2e	71a(4mm)	Hit	BA182,BA243,BA283,BA483..484,+

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1S27	Ge-Di	Gl-L,70V,10A	-	Njr	-
1S270	Z-Di	=1S262:13V	32a$	-	-
1S2701(R)	Si-Di	Gl-L,100V,100A(Tc=96o)	-	Nec	-
1S2702(R)	Si-Di	=1S2701:200V	-		-
1S2703(R)	Si-Di	=1S2701:300V	-		-
1S271	Z-Di	=1S262:14V	32a$	-	-
1S2711	Si-Di	Gl,1500V,1,5A	34a$	Tos	BY228,BY255,BY400,BY448
1S2712	Si-Di	Gl,S,1800V,1,4A,<2,2?s	34b&	Tos	-
1S2713	Si-Di	kV-Gl,45kV,2A	-	Tos	-
1S2714	Si-Di	Gl/S-L,100V,6A(Tc=100o),<200ns	32	Tos	1N3880..3883
1S2715	Si-Di	=1S2714:200V	32	-	1N3881..3883
1S2716	Si-Di	=1S2714:300V	32	-	1N3882..3883
1S2717	Si-Di	=1S2714:400V	32	-	1N3883
1S2718	Si-Di	=1S2714:600V	32	-	-
1S2719	Si-Di	Gl/S-L,100V,30A(Tc=100o),<200ns	32	Tos	1N3910..3913
1S272	Z-Di	=1S262:15V	32a$	-	-
1S2720	Si-Di	=1S2719:200V	32	-	1N3911..3913
1S2721	Si-Di	=1S2719:300V	32	-	1N3912..3913
1S2722	Si-Di	=1S2719:400V	32	-	1N3913
1S2723	Si-Di	=1S2719:600V	32	-	-
1S2724	Si-Di	Dual,200V,5A	22l$	Sak	-
1S2724R..2726R	Si-Di	=1S2724:	22m&	-	-
1S2725	Si-Di	=1S2724:400V	22l$	-	-
1S2726	Si-Di	=1S2724:600V	22l$	-	-
1S273	Z-Di	=1S262:16V	32a$	-	-
1S274	Z-Di	=1S262:17V	32a$	-	-
1S2745	Si-Di	Gl,S,750V,2,5A,<1,3?s	34b&	Tos	BY228,BY438,RGP30K
1S2746	Si-Di	=1S2745:800V	34b&	-	BY228,BY438,RGP30K
1S2747	Si-Di	=1S2745:1000V	34b&	-	BY228,BY438,RGP30M
1S275	Z-Di	=1S262:18V	32a$	-	-
1S2756	Si-Di	Gl,Uni,400V,1A,<2,5?s	31a	Tos	BY201/4,BYX55/600,RGP10G
1S2757	Si-Di	=1S2756:600V	31a	-	BY201/6,BYX55/600,RGP10J
1S2758	Si-Di	Gl,Uni,1000V,3A	31a	Nec	BY255,BYW17/1000,G3M,1N5408,+
1S2759	Si-Di	=1S2758:1200V	31a	-	BY255,BYW17/1200
1S276	Z-Di	=1S262:19V	32a$	-	-
1S2760	Si-Di	=1S2758:50V	31a	-	BY251..255,BYW17/100,1N5402..08,+
1S2761	Si-Di	=1S2758:100V	31a	-	BY251..255,BYW17/100,1N5402..08,+
1S2762	Si-Di	=1S2758:200V	31a	-	BY251..255,BYW17/200,1N5402..08,+
1S2763	Si-Di	=1S2758:300V	31a	-	BY252..255,BYW17/400,1N5403..08,+
1S2764	Si-Di	=1S2758:400V	31a	-	BY252..255,BYW17/400,1N5404..08,+
1S2765	Si-Di	=1S2758:500V	31a	-	BY253..255,BYW17/600,1N5406..08,+
1S2766	Si-Di	=1S2758:600V	31a	-	BY253..255,BYW17/600,1N5406..08,+
1S2766A	Si-Di	=1S2766:contr.av.	31a	-	BYM56C,BYW18/600,BYW84..86
1S2767	Si-Di	=1S2758:700V	31a	-	BY254..255,BYW17/800,1N5407..08,+
1S2767A	Si-Di	=1S2767:contr.av.	31a	-	BYM56D,BYW18/800,BYW85..86
1S2768	Si-Di	=1S2758:800V	31a	-	BY254..255,BYW17/800,1N5407..08,+
1S2768A	Si-Di	=1S2768:contr.av.	31a	-	BYM56D,BYW18/800,BYW85..86
1S2769	Ref-Di	6..7V,0,25W	2a	Nec	BZV10,BZV27,1N4580
1S277	Z-Di	=1S262:20V	32a$	-	-
1S2770	Ref-Di	6..7V,0,25W	2a	-	BZV10,BZV27,1N4580
1S2771	Ref-Di	6..7V,0,25W	2a	-	BZV11,BZV28,1N4581
1S2772	Ref-Di	6..7V,0,25W	2a	-	BZV12,BZV29,1N4582
1S2773	Ref-Di	6..7V,0,25W	2a	-	BZV13,BZV30,1N4583
1S2774	Ref-Di	6..7V,0,25W	2a	-	BZV14,BZV31,1N4584
1S2775	Si-Di	Gl,Uni,200V,0,5A,<2?s	31a	Tos	BY295/200,BY406..407,BYX55/600,+
1S2776	Si-Di	=1S2775:400V	31a	-	BY295/400,BY407,BYX55/600,+
1S2777	Si-Di	=1S2775:600V	31a	-	BY295/600,BY407,BYX55/600,+
1S2778	Si-Di	Gl,Uni,200V,2,7A	31a	Sak	BY251..255,GP30D,MR502..510,+
1S2779	Si-Di	=1S2778:400V	31a	-	BY252..255,GP30G,MR504..510,+
1S278	Z-Di	=1S262:22V	32a$	-	-
1S2780	Si-Di	=1S2778:600V	31a	-	BY253..255,GP30J,MR506..510,+
1S2781	Si-Di	=1S2778:800V	31a	-	BY254..255,GP30K,MR508..510,+
1S2782	Si-Di	=1S2778:1000V	31a	-	BY228,BY255,GP30M,MR510,+
1S2783	C-Di	Tuning,30V,1,8..2,8pF(25V)	31a	Njr	-

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1S2784	Si-Br	GI-Br,100V,0,5A	42	Stl	B100C500,etc.
1S2785	Si-Br	=1S2784:200V	42	-	B200C500,etc.
1S2786	Si-Br	=1S2784:400V	42	-	B400C500,etc.
1S2787	Si-Di	SS,40V,0,05A,<3ns	31a	Rhm	BA318,BAY38,1N4148..49,1N4446..49+
1S2788	Si-Di	SS,25V,0,05A,<3ns	31a	Rhm	BA318,BAY38,1N4148..49,1N4446..49+
1S2789	C-Di	UHF-Tuning,30V,11,5/2o2,65pF(3/25V)	71a(4mm)	Tos	BB105,BB205,BB305,BB405,BB505+
1S279	Z-Di	=1S262:24V	32a$	-	-
1S2790	C-Di	VHF-AFC,20V,14..26pF(10V)	31a	Hit	BA125,BB119,1SV114,1SV125
1S2791	Si-Di	Schottky-Di,UHF-M,5V,30mA,887MHz	31a	Hit	BA480..481,BAR19,BAT29
1S2792	Si-Di	GI/S-L,100V,20A(Tc=90o),<300ns	32b&	Sak	1N3900R..3903R
1S2793	Si-Di	=1S2792:250V	32b&	-	1N3902R..3903R
1S2794	Si-Di	=1S2792:400V	32b&	-	1N3903R
1S2795	Si-Di	GI-L,400V,12A(Tc=40o)	32	Tos	-
1S2796	Si-Di	=1S2795:600V	32	-	-
1S2797	Si-Di	=1S2795:800V	32	-	-
1S2798	Si-Di	=1S2795:1000V	32	-	-
1S2799	Si-Di	GI-L,100V,150A(Tc=76o)	73	Inr	1N4587..4596
1S28	Ge-Di	GI-L,50V,0,5A	734a$	Njr	-
1S280	Z-Di	=1S262:25V	32a$	-	-
1S2800	Si-Di	=1S2799:200V	73	-	1N4588..4596
1S2801	Si-Di	=1S2799:300V	73	-	1N4589..4596
1S2802	Si-Di	=1S2799:400V	73	-	1N4590..4596
1S2803	Si-Di	=1S2799:600V	73	-	1N4592..4596
1S2804	Si-Di	=1S2799:800V	73	-	1N4593..4596
1S2805	Si-Di	=1S2799:1000V	73	-	1N4594..4596
1S2806	Si-Di	=1S2799:1200V	73	-	1N4595..4596
1S2807	Si-Di	=1S2799:1400V	73	-	1N4596
1S2808	Si-Di	=1S2799:1600V	73	-	-
1S2809	Si-Di	GI-L,100V,250A(Tc=74o)	73	Inr	1N3735..3744
1S281	Z-Di	=1S262:27V	32a$	-	-
1S2810	Si-Di	=1S2809:200V	73	-	1N3736..3744
1S2811	Si-Di	=1S2809:300V	73	-	1N3737..3744
1S2812	Si-Di	=1S2809:400V	73	-	1N3738..3744
1S2813	Si-Di	=1S2809:600V	73	-	1N3740..3744
1S2814	Si-Di	=1S2809:800V	73	-	1N3741..3744
1S2815	Si-Di	=1S2809:1000V	73	-	1N3742..3744
1S2816	Si-Di	=1S2809:1200V	73	-	1N3743..3744
1S2817	Si-Di	=1S2809:1400V	73	-	1N3744
1S2818	Si-Di	=1S2809:1600V	73	-	-
1S2819	Si-Di	GI-L,600V,500A(Tc=100o)	73	Inr	-
1S282	Z-Di	=1S262:30V	32a$	-	-
1S2820	Si-Di	=1S2819:800V	73	-	-
1S2821	Si-Di	=1S2819:1000V	73	-	-
1S2822	Si-Di	=1S2819:1200V	73	-	-
1S2823	Si-Di	=1S2819:1400V	73	-	-
1S2824	Si-Di	=1S2819:1600V	73	-	-
1S2825	Si-Di	=1S2819:1800V	73	-	-
1S2826(A)	Si-Di	GI,Uni,100V,1,5A	31a	Sak	BY226..227,BY251..255,1N5401..08,+
1S2827(A)	Si-Di	=1S2826:200V	31a	-	BY226..227,BY251..255,1N5402..08,+
1S2828(A)	Si-Di	=1S2826:400V	31a	-	BY226..227,BY252..255,1N5404..08,+
1S2829(A)	Si-Di	=1S2826:600V	31a	-	BY226..227,BY253..255,1N5406..08,+
1S283	Z-Di	=1S262:33V	32a$	-	-
1S2830(A)	Si-Di	=1S2826:800V	31a	-	BY227,BY254..255,1N5407..08,+
1S2831(A)	Si-Di	=1S2826:1000V	31a	-	BY227,BY228,BY255,1N5408,+
1S2832	Si-Di	GI,Uni,200V,1A	31a	Sak	BY126..127,BY226..227,1N4003..07,+
1S2833	Si-Di	=1S2832:800V	31a	-	BY127,BY227,GP10Q,1N4006..07,+
1S2834	Si-Di	=1S2832:1200V	31a	-	BY127,BY227,EM513,GP10Q,+
1S2835	Si-Di	SMD,Dual,SS,35V,0,15A,<4ns	35m	Nec	MA151WA,MA152WA,1SS181
1S2836	Si-Di	=1S2835:75V	35m	-	BAW56,MA152WA,1SS181
1S2837	Si-Di	=1S2835:	35l	-	MA151WK,MA152WK,1SS184
1S2838	Si-Di	=1S2835:75V	35l	-	BAV70,MA152WK,1SS184
1S2839	Si-Di	GI,Uni,600V,1A,1,5?s	34b&	Tos	BY201/6,BYX55/600,RGP10J,+
1S284	Z-Di	=1S262:36V	32a$	-	-
1S285	Z-Di	=1S262:39V	32a$	-	-

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1S286	Z-Di	=1S262:43V	32a$	-	-
1S287	Z-Di	=1S262:45V	32a$	-	-
1S288	Z-Di	=1S262:47V	32a$	-	-
1S289	Z-Di	=1S262:50V	32a$	-	-
1S29	Ge-Di	=1S28:150V	?34a$	Njr	-
1S290	Z-Di	=1S262:52V	32a$	-	-
1S291	Z-Di	=1S262:56V	32a$	-	-
1S292	Z-Di	=1S262:62V	32a$	-	-
1S293	Z-Di	=1S262:68V	32a$	-	-
1S294	Z-Di	=1S262:75V	32a$	-	-
1S295	Z-Di	=1S262:82V	32a$	-	-
1S296	Z-Di	=1S262:91V	32a$	-	-
1S297	Z-Di	=1S262:100V	32a$	-	-
1S298	Z-Di	=1S262:105V	32a$	-	-
1S299	Z-Di	=1S262:110V	32a$	-	-
1S30	Ge-Di	=1S28:250V	?34a$	Njr	-
1S300	Z-Di	=1S262:120V	32a$	-	-
1S3006(A)	Z-Di	6,8V,1W,10%,(A=5%)	31a	Tix	BZW22/..,BZX61/..,ZPY..,1N5921..56,+
1S3007(A)	Z-Di	=1S3006(A):7,5V	31a	-	-
1S3008(A)	Z-Di	=1S3006(A):8,2V	31a	-	-
1S3009(A)	Z-Di	=1S3006(A):9,1V	31a	-	-
1S301	Z-Di	=1S262:130V	32a$	-	-
1S3010(A)	Z-Di	=1S3006(A):10V	31a	-	-
1S3011(A)	Z-Di	=1S3006(A):11V	31a	-	-
1S3012(A)	Z-Di	=1S3006(A):12V	31a	-	-
1S3013(A)	Z-Di	=1S3006(A):13V	31a	-	-
1S3015(A)	Z-Di	=1S3006(A):15V	31a	-	-
1S3016(A)	Z-Di	=1S3006(A):16V	31a	-	-
1S3018(A)	Z-Di	=1S3006(A):18V	31a	-	-
1S302	Z-Di	=1S262:140V	32a$	-	-
1S3020(A)	Z-Di	=1S3006(A):20V	31a	-	-
1S3022(A)	Z-Di	=1S3006(A):22V	31a	-	-
1S3024(A)	Z-Di	=1S3006(A):24V	31a	-	-
1S3027(A)	Z-Di	=1S3006(A):27V	31a	-	-
1S303	Z-Di	=1S262:150V	32a$	-	-
1S3030(A)	Z-Di	=1S3006(A):30V	31a	-	-
1S3033(A)	Z-Di	=1S3006(A):33V	31a	-	-
1S3036(A)	Z-Di	=1S3006(A):36V	31a	-	-
1S3039(A)	Z-Di	=1S3006(A):39V	31a	-	-
1S304	Ref-Di	8..9V,0,2W,n0,002%/oC	2	Nec	-
1S3043(A)	Z-Di	=1S3006(A):43V	31a	-	-
1S3047(A)	Z-Di	=1S3006(A):47V	31a	-	-
1S305	Ref-Di	8..9V,0,2W,n0,005%/oC	2	Nec	-
1S3051(A)	Z-Di	=1S3006(A):51V	31a	-	-
1S3056(A)	Z-Di	=1S3006(A):56V	31a	-	-
1S306(-M)	Si-Di	SS,35V,0,06A,<3ns,-M:<4ns	31a	Nec	BA218,BAX13,BAY71,1N4148..49,+
1S3062(A)	Z-Di	=1S3006(A):62V	31a	-	-
1S3068(A)	Z-Di	=1S3006(A):68V	31a	-	-
1S307	Ge-Di	S,20V,0,085A,<100ns	31a	Nec	AAY27,AAZ18
1S3075(A)	Z-Di	=1S3006(A):75V	31a	-	-
1S308	Ge-Di	Gl,Uni,80V,0,2A	34	Hit	-
1S3082(A)	Z-Di	=1S3006(A):82V	31a	-	-
1S309	Ge-Di	Gl,Uni,120V,0,25A	34	Hit	-
1S3091(A)	Z-Di	=1S3006(A):91V	31a	-	-
1S30N06L	MOS-N-FET-e	=RF1S30N06LE(Typ-Code/Stempel/marking)	30	Rca	→RF1S30N06LE
1S31	Ge-Di	=1S28:300V	?34a$	Njr	-
1S310(H)	Si-Di	Gl,Uni,50V,0,5A	31a	Hit	BY126..127,BY133..135,1N4001..07,+
1S3100(A)	Z-Di	=1S3006(A):100V	31a	-	-
1S311(H,N)	Si-Di	=1S310:100V	31a	-	BY126..127,BY133..135,1N4002..07,+
1S3110(A)	Z-Di	=1S3006(A):110V	31a	-	-
1S312(A,H)	Si-Di	=1S310:200V	31a	-	BY126..127,BY133..134,1N4003..07,+
1S3120(A)	Z-Di	=1S3006(A):120V	31a	-	-
1S313(H)	Si-Di	=1S310:300V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S3130(A)	Z-Di	=1S3006(A):130V	31a	-	-

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1S314(H,N)	Si-Di	=1S310:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S315(H)	Si-Di	=1S310:500V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S3150(A)	Z-Di	=1S3006(A):150V	31a	-	-
1S316	Si-Di	=1S310:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S3160(A)	Z-Di	=1S3006(A):160V	31a	-	-
1S317	Si-Di	=1S310:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S318	Ge-Di	Uni,75V,0,05A	31a	Gie	AA117..118,AA132..133,1N634..635
1S3180(A)	Z-Di	=1S3006(A):180V	31a	-	-
1S319	Ge-Di	Uni,60V,0,04A	31a	Gie	AA117..118,AA132..134,1N34,1N54,+
1S32	Ge-Di	Uni,75V,30mA	31a	Tos	AA117..118,AA132..133,1N634
1S320	Ge-Di	Dem,40V,0,05A	31a	Gie	AA113,AA119,1N34,1N54,1N60
1S3200(A)	Z-Di	=1S3006(A):200V	31a	-	-
1S321	Ge-Di	Uni,120V,0,05A	31a	Gie	AA133,1N635
1S322	Ge-Di	Uni,75V,0,04A	31a	Gie	AA117..118,AA132..133,1N634..635
1S323	Ge-Di	Uni,50V,0,05A	31a	Gie	AA117..118,AA132..134,1N34,1N54,+
1S324	Si-Di	SS,40V,0,04A,<3ns	31a	Tos	BA218,BAX13,BAX91,1N4148..49,+
1S325	Si-Di	SS,40V,0,04A,<3ns	31a	Tos	BA218,BAX13,BAX91,1N4148..49,+
1S326	Si-Di	Gl,Uni,200V,0,5A	34a$	Njr	BY126..127,BY133..134,1N4003..07,+
1S327	Si-Di	=1S326:400V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S328	Si-Di	=1S326:600V,0,4A	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S329	Si-Di	=1S326:800V,0,4A	34a$	-	BY127,BY133,BY227,1N4006..07,+
1S33	Ge-Di	Uni,120V,30mA	31a	Tos	AA132..133,1N634
1S330	Z-Di	4,4..5,6V,0,25W	31a	Njr	BZX55/..,BZX79/..,ZPD..,1N5230..50,+
1S331	Z-Di	=1S330:5,4..6,6V	31a	-	-
1S332	Z-Di	=1S330:6,4..7,6V	31a	-	-
1S333	Z-Di	=1S330:7,4..8,6V	31a	-	-
1S334	Z-Di	=1S330:8,4..9,6V	31a	-	-
1S335	Z-Di	=1S330:9,4..10,6V	31a	-	-
1S336	Z-Di	=1S330:10,4..11,6V	31a	-	-
1S337	Z-Di	=1S330:11,4..12,6V	31a	-	-
1S338	Z-Di	=1S330:12,4..16,1V	31a	-	-
1S339	Z-Di	=1S330:15,9..20V	31a	-	-
1S34	Ge-Di	Uni,75V,30mA	31a	Tos	AA117..118,AA132..133,1N634
1S340	Z-Di	4,4..5,6V,1,5W	?34a$	Njr	BZV47/..,BZY97/..,ZY..,1N5917..32,+
1S341	Z-Di	=1S340:5,4..6,6V	?34a$	-	-
1S342	Z-Di	=1S340:6,4..7,6V	?34a$	-	-
1S343	Z-Di	=1S340:7,4..8,6V	?34a$	-	-
1S344	Z-Di	=1S340:8,4..9,6V	?34a$	-	-
1S345	Z-Di	=1S340:9,4..10,6V	?34a$	-	-
1S346	Z-Di	=1S340:10,4..11,6V	?34a$	-	-
1S347	Z-Di	=1S340:11,4..12,6V	?34a$	-	-
1S348	Z-Di	=1S340:12,4..16,1V	?34a$	-	-
1S349	Z-Di	=1S340:15,9..20V	?34a$	-	-
1S35	Ge-Di	4x Di,Ringmodulator,30V,0,12A	-	Tos	-
1S350	Ge-Di	Dem,30V,15mA	31a	Njr	AA113,AA119,1N34,1N54,1N60
1S351(M,S)	C-Di	AFC(25MHz),35V,8..18pF(10V)	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S352(M,N)	C-Di	AFC(25MHz),35(N=60V)V,8..18pF(10V)	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S353(M)	C-Di	AFC,20V,22..38pF(10V)	31a	Njr	BA124..125,BB119,1S2790,1SV50,+
1S354	Ge-Di	Uni,75V,0,04A	31a	Njr	AA117..118,AA132..133,1N634..635
1S355	Ge-Di	Dem,30V,0,05A	31a	Njr	AA113,AA119,1N34,1N54,1N60,+
1S356	Ge-Di	Dem,Uni,50V,0,06A	31a	Njr	AA113,AA117..118,1N34,1N60,+
1S357	Ge-Di	Dem,45V,0,05A	31a	Njr	AA113,AA119,1N34,1N54,1N60,+
1S358	Si-Di	Uni,150V,0,1A	31a	Njr	BA147/150,BA189..190,1N5606..07,+
1S358-S	Si-Di	=1S358:50V	31a	-	BA147/50,BA187..190,1N5606..09,+
1S359	Si-Di	Gl,Uni,400V,0,5A	31a	Nec	BY126..127,BY133..134,1N4004..07,+
1S36	Si-Di	Gl,Uni,200V,0,5A	?34a$	Mat	BY126..127,BY133..134,1N4003..07,+
1S360	Si-Di	UHF-Varaktor,30GHz,5V,30mA	Koax	Nec	-
1S361	Si-Di	UHF-Varaktor,50GHz,5V,30mA	Koax	Nec	-
1S362	Si-Di	UHF-Varaktor,70GHz,5V,30mA	Koax	Nec	-
1S363	Si-Di	UHF-Varaktor,90GHz,5V,30mA	Koax	Nec	-
1S364	Ge-Di	FM/VHF-AFC,20V,20..40/2..6pF(1/10V)	4	Njr	-
1S365	Ge-Di	=1S364:10..20/1,5..4,5pF(1/10V)	4	Njr	-
1S366	Ge-Di	=1S364:5..10/1..3pF(1/10V)	4	Njr	-
1S367	Si-Di	Gl,Uni,100V,0,4A	34a$	Njr	BY126..127,BY133..135,1N4002..07,+

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1S368	Si-Di	=1S367:200V	34a$	-	BY126..127,BY133..134,1N4003..07,+
1S369	Si-Di	=1S367:300V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S37	Si-Di	=1S36:400V	?34a$	Mat	BY126..127,BY133..134,1N4004..07,+
1S370	Si-Di	=1S367:400V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S371	Si-Di	=1S367:500V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S372	Si-Di	=1S367:600V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S373	Si-Di	GI,Uni,100V,0,3A	34	Inr	BY126..127,BY133..135,1N4002..07,+
1S374	Si-Di	=1S373:200V	34	-	BY126..127,BY133..134,1N4003..07,+
1S375	Si-Di	=1S373:400V	34	-	BY126..127,BY133..134,1N4004..07,+
1S376	Si-Di	=1S373:500V	34	-	BY126..127,BY133..134,1N4005..07,+
1S377	Si-Di	=1S373:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S378	Si-Di	GI,Uni,100V,0,3A	34	Inr	BY126..127,BY133..135,1N4002..07,+
1S379	Si-Di	=1S378:200V	34	-	BY126..127,BY133..134,1N4003..07,+
1S38	Si-Di	=1S36:700V	?34a$	Mat	BY127,BY133,BY227,1N4006..07,+
1S380	Si-Di	=1S378:400V	34	-	BY126..127,BY133..134,1N4004..07,+
1S381	Si-Di	=1S378:500V	34	-	BY126..127,BY133..134,1N4005..07,+
1S382	Si-Di	=1S378:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S383	Si-Di	GI-L,100V,0,8A(Tc=70o)	32a$	Inr	(BY126..127,BY133..135,1N4002..07++)
1S384	Si-Di	=1S383:200V	32a$	-	(BY126..127,BY133..134,1N4003..07++)
1S385	Si-Di	=1S383:400V	32a$	-	(BY126..127,BY133..134,1N4004..07++)
1S386	Si-Di	=1S383:500V	32a$	-	(BY126..127,BY133..134,1N4005..07++)
1S387	Si-Di	=1S383:600V	32a$	-	(BY126..127,BY133..134,1N4005..07++)
1S388	Si-Di	GI-L,100V,0,8A(Tc=70o)	32a$	Inr	(BY126..127,BY133..135,1N4002..07++)
1S389	Si-Di	=1S388:200V	32a$	-	(BY126..127,BY133..134,1N4003..07++)
1S39	Si-Di	=1S36:800V,0,4A	?34a$	Mat	BY127,BY133,BY227,1N4006..07,+
1S390	Si-Di	=1S388:400V	32a$	-	(BY126..127,BY133..134,1N4004..07++)
1S391	Si-Di	=1S388:500V	32a$	-	(BY126..127,BY133..134,1N4005..07++)
1S392	Si-Di	=1S388:600V	32a$	-	(BY126..127,BY133..134,1N4005..07++)
1S393	Si-Di	GI,Uni,400V,0,3A	?31a	Inr	BA157..159,BY204/4,BY206..207,+
1S394	Si-Di	=1S393:0,4A	?31a	-	BA157..159,BY204/4,BY206..207,+
1S395	Si-Di	GI,Uni.400V,0,5A	31a	Inr	BY126..127,BY133..134,1N4004..07,+
1S396	Si-Di	=1S395:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S397	Si-Di	=1S395:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S398	Si-Di	=1S395:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S399	Si-Di	-	34	IRF	BY126..127,BY133..134,1N4004..07..
1S399[IR]	Si-Di	GI,Uni,400V,0,8A	34	Inr	BY126..127,BY133..134,1N4004..07,+
1S40	Si-Di	GI,Uni,100V,0,75A	34a	Fui	BY126..127,BY133..135,1N4002..07,+
1S400	Si-Di	-	34	IRF	BY126..127,BY133..134,1N4005..07..
1S400[IR]	Si-Di	=1S399[IR]:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S4006..4200(A)	Z-Di	=1S3006..3200(A):1,5W	34a$	Tix	BZV47/..,BZY97/..,ZY..,1N5921..56,+
1S401	Si-Di	-	34	IRF	BY127,BY133,BY227,1N4006..07..
1S401(R)	Si-Di	-		TI	1S420(R)[Texas]
1S401(R)[Texas]	Si-Di	=1S420(R)[Texas]	-	Tix	→1S420(R)[Texas]
1S401[IR]	Si-Di	=1S399[IR]:800V	34	-	BY127,BY133,BY227,1N4006..07,+
1S401[R]	Si-Di	-		TI	1S420(R)[Texas]
1S402	Si-Di	-	34	IRF	BY127,BY133,BY227,1N4007..
1S402(R)	Si-Di	-		TI	1S421(R)[Texas]
1S402(R)[Texas]	Si-Di	=1S421(R)[Texas]	-	Tix	→1S421(R)[Texas]
1S402[IR]	Si-Di	=1S399[IR]:1000V	34	-	BY127,BY133,BY227,1N4007,+
1S402[R]	Si-Di	-		TI	1S421(R)[Texas]
1S403	Si-Di	-	34	IRF	BY127,BY133,BY227,GP10Q..
1S403(R)	Si-Di	-		TI	1S422(R)[Texas]
1S403(R)[Texas]	Si-Di	=1S422(R)[Texas]	-	Tix	→1S422(R)[Texas]
1S403[IR]	Si-Di	=1S399[IR]:1200V	34	-	BY127,BY133,BY227,GP10Q,+
1S403[R]	SI-Di	-		TI	1S422(R)[Texas]
1S404	Si-Di	-	31a	IRF	BA157..159,BAY89..91,BY203/12..
1S404(R)	Si-Di	-		TI	1S423(R)[Texas]
1S404(R)[Texas]	Si-Di	=1S423(R)[Texas]	-	Tix	→1S423(R)[Texas]
1S404[IR]	SI-Di	GI,Uni,600V,0,1A	31a	Inr	BA157..159,BAY89..91,BY203/12,+
1S404[R]	Si-Di	-		TI	1S423(R)[Texas]
1S405	Si-Di	-	31a	IRF	BA159;BAY90..91,BY203/12..
1S405(R)	SI-Di	-		TI	1S424(R)[Texas]
1S405(R)[Texas]	Si-Di	=1S424(R)[Texas]	-	Tix	→1S424(R)[Texas]
1S405[IR]	Si-Di	=1S404[IR]:800V	31a	-	BA159,BAY90..91,BY203/12,+

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1S405[R]	Si-Di	-		TI	1S424(R)[Texas]
1S406	Si-Di	-	31a	IRF	BA159,BAY90..91,BY203/12..
1S406(R)	Si-Di	-		TI	1S425(R)[Texas]
1S406(R)[Texas]	Si-Di	=1S425(R)[Texas]	-	Tix	→1S425(R)[Texas]
1S406[IR]	Si-Di	=1S404[IR]:1000V	31a	-	BA159,BAY90..91,BY203/12,+
1S406[R]	Si-Di	-		TI	1S425(R)[Texas]
1S407	Si-Di	-	31a	IRF	BAY91,BY203/12,BY584,SHG1,5..
1S407(R)	Si-Di	-		TI	1S426(R)[Texas]
1S407(R)[Texas]	Si-Di	=1S426(R)[Texas]	-	Tix	→1S426(R)[Texas]
1S407[IR]	Si-Di	=1S404[IR]:1200V	31a	-	BAY91,BY203/12,BY584,SHG1,5,+
1S407[R]	Si-Di	-		TI	1S426(R)[Texas]
1S408	Si-Di	-	31a	IRF	1N1732A
1S408(R)	Si-Di	-		TI	1S427(R)[Texas]
1S408(R)[Texas]	Si-Di	=1S427(R)[Texas]	-	Tix	→1S427(R)[Texas]
1S408[IR]	Si-Di	kV-Gl,1,5kV,0,38A	31a	Inr	1N1732A
1S408[R]	Si-Di	-		TI	1S427(R)[Texas]
1S409	Si-Di	-	31a	IRF	1N1732A
1S409[IR]	Si-Di	=1S408[IR]:1,8kV	31a	-	1N1732A
1S41	Si-Di	=1S40:200V	34a	-	BY126..127,BY133..134,1N4003..07,+
1S410	Si-Di	-	32a$	TI	BYX38/300,BYX39/600
1S410[IR]	Si-Di	=1S408[IR]:2,4kV	31a	-	1N1733A
1S410[Texas]	Si-Di	Gl-L,100V,3A(Tc=125o)	32a$	Tix	BYX38/300,BYX39/600
1S410R..19R[Texas]	Si-Di	=1S410..419[Texas]:	32b&	-	BYX38/..R,BYX39/..R
1S410R..419R	Si-Di	-	32b&	TI	BYX38/..R,BYX39/..R
1S411	Si-Di	-	32a$	TI	BYX38/300,BYX39/600
1S411[IR]	Si-Di	=1S408[IR]:3,6kV,0,36A	31a	-	1N1734A
1S411[Texas]	Si-Di	=1S410[Texas]:200V	32a$	-	BYX38/300,BYX39/600
1S412	Si-Di	-	31a	IRF	1N1734A
1S412[IR]	Si-Di	=1S408[IR]:4,8kV,0,36A	31a	-	1N1734A
1S413[IR]	Si-Di	=1S408[IR]:6kV,0,36A	31a	-	-
1S413[Texas]	Si-Di	=1S410[Texas]:400V	32a$	-	BYX38/600,BYX39/600
1S414	Si-Di	-	31a	IRF	-
1S414[IR]	Si-Di	=1S408[IR]:7,2kV,0,33A	31a	-	-
1S415[IR]	Si-Di	=1S408[IR]:12kV,0,25A	31a	-	-
1S415[Texas]	Si-Di	=1S410[Texas]:600V	32a$	-	BYX38/600,BYX39/600
1S416	Si-Di	-	31a	IRF	-
1S416[IR]	Si-Di	=1S408[IR]:16kV,0,25A	31a	-	-
1S417	Si-Di	-	32a$	IRF	BYX38/300,BYX39/600
1S417[IR]	Si-Di	Gl-L,50V,3A(Tc=70o)	32a$	Inr	BYX38/300,BYX39/600
1S417[Texas]	Si-Di	=1S410[Texas]:800V	32a$	-	BYX38/900,BYX39/800
1S418	Si-Di	-	32a$	IRF	BYX38/300,BYX39/600
1S418[IR]	Si-Di	=1S417[IR]:100V	32a$	-	BYX38/300,BYX39/600
1S419[IR]	Si-Di	=1S417[IR]:150V	32a$	-	BYX38/300,BYX39/600
1S419[Texas]	Si-Di	=1S410[Texas]:1000V	32a	-	BYX38/1200,BYX39/1000
1S42	Si-Di	=1S40:300V	34a	-	BY126..127,BY133..134,1N4004..07,+
1S420	Si-Di	-	32a$	TI	BYW88/100,BYX76..81,1N4506..11,+
1S420[IR]	Si-Di	=1S417[IR]:200V	32a	-	BYX38/300,BYX39/600
1S420[Texas]	Si-Di	Gl-L,100V,10A(Tc=100o)	32a$	Tix	BYW88/100,BYX76..81,1N4506..11,+
1S420R..27R[Texas]	Si-Di	=1S420[Texas]:800V	32b&	-	BYW88/..R,BYX86R..81R
1S420R..427R	Si-Di	-	32b&	TI	BYW88/..R,BYX86R..81R
1S421[IR]	Si-Di	=1S417[IR]:250V	32a	-	BYX38/300,BYX39/600
1S421[Texas]	Si-Di	=1S420[Texas]:200V	32a$	-	BYW88/200,BYX77..81,1N4506..11,+
1S422	Si-Di	-	32a	IRF	BYX38/300,BYX39/600
1S422[IR]	Si-Di	=1S417[IR]:300V	32a	-	BYX38/300,BYX39/600
1S423[IR]	Si-Di	=1S417[IR]:400V	32a	-	BYX38/600,BYX39/600
1S423[Texas]	Si-Di	=1S420[Texas]:400V	32a$	-	BYW88/400,BYX78..81,1N4507..11,+
1S424	Si-Di	-	32a	IRF	BYX38/600,BYX39/600
1S424[IR]	Si-Di	=1S417[IR]:500V	32a	-	BYX38/600,BYX39/600
1S425[IR]	Si-Di	=1S417[IR]:600V	32a	-	BYX38/600,BYX39/600
1S425[Texas]	Si-Di	=1S420[Texas]:600V	32a$	-	BYW88/600,BYX79..81,1N4508..11,+
1S426(G)	Ge-Diode	Demodulator,15(G=25)V,20(G=50)mA	31a	Sanyo	AA112..114,1N34,1N54,1N60..
1S426(G)[Japan]	Ge-Di	Dem,15(G=25)V,20(G=50)mA	31a	Say	AA112..114,1N34,1N54,1N60,+
1S427	Z-Di	13,5..15V,0,3W	31a	Tos	BZX55/C1S,BZX79/C1S,ZPD1S,1N5244
1S427[Japan]	Z-Di	13,5..15V,0,3W	31a	Tos	BZX55/C1S,BZX79/C1S,ZPD1S,1N5244

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1S427[Texas]	Si-Di	=1S420[Texas]: 800V	32a$	-	BYW88/800, BYX80..81, 1N4509..11,+
1S43	Si-Di	=1S40: 400V	34a	-	BY126..127, BY133..134, 1N4004..07,+
1S431	Si-Di	Gl-L, 100V, 100A(Tc=105o)	73a$	Nec	1N3288..97
1S432	Si-Di	=1S431: 200V	73a$	-	1N3289..97
1S433	Si-Di	=1S431: 300V	73a$	-	1N3290..97
1S434	Si-Di	=1S431: 400V	73a$	-	1N3291..97
1S435	Si-Di	=1S431: 500V	73a$	-	1N3292..97
1S436	SI-Di	=1S431: 600V	73a$	-	1N3293..97
1S437	Si-Di	=1S431: 700V	73a$	-	1N3294..97
1S438	Si-Di	=1S431: 800V	73a$	-	1N3294..97
1S439	Si-Di	=1S431: 900V	73a$	-	1N3295..97
1S44	Si-Di	=1S40: 500V	34a	-	BY126..127, BY133..134, 1N4005..07,+
1S44[Texas]	Si-Di	SS, 40V, 0,1A, <8ns	31a	Fch, Tix	BA318, BAY38, 1N4148..49, 1N4151,+
1S440	SI-Di	=1S431: 1000V	73a$	-	1N3295..97
1S441	Ge-Di	Dem, Uni, 45V, 30mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S442	Ge-Di	Dem, Uni, 43V, 0,1A	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S443	Ge-Di	S, 43V, 0,12A, <2?s	31a	Fui	AA136, AAY49, AAZ15, AAZ17
1S444	Ge-Di	S, 30V, 0,09A, <200ns	31a	Fui	AAY49, AAZ15, AAZ17
1S445	Ge-Di	S, 65V, 0,1A, <450ns	31a	Fui	AAZ15, AAZ17
1S446	Ge-Di	Dem, Uni, 60V, 30mA	31a	Fui	AA113, 1N34, 1N54, 1N60
1S447	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S448	Ge-Di	Dem, Uni, 110V, 40mA	31a	Fui	AA117..118, AA132..133
1S449	Ge-Di	Dem, Uni, 110V, 40mA	31a	Fui	AA117..118, AA132..133
1S45	Si-Di	=1S40: 600V	34a	Fui	BY126..127, BY133..134, 1N4005..07,+
1S450	Ge-Di	Uni, 140V, 30mA	?2c	Fui	AA133
1S451	Ge-Di	Dem, Uni, 60V, 40mA	31a	Fui	AA113, 1N43, 1N54, 1N60
1S452	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S453	Ge-Di	Dem, Uni, 75V, 40mA	31a	Fui	AA117..118, AA132..133
1S454	Ge-Di	Dem, Uni, 45V, 40mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S455	Ge-Di	Dem, Uni, 35V, 40mA	31a	Fui	AA113, AA119, 1N34, 1N54, 1N60
1S456	Si-Di	Gl, Uni, 40V, 0,1A	31a	Fui	BA147/50, BA187..190, 1N5606..09,+
1S457	Si-Di	=1S456: 80V	31a	-	BA147/100, BA188..190, 1N5606..09,+
1S458	Si-Di	=1S456: 150V	31a	-	BA147/150, BA189..190, 1N5606..07,+
1S459	Si-Di	=1S456: 200V	31a	-	BA147/230, BA190, 1N5606..07,+
1S46	Si-Di	=1S40: 700V	34a	Fui	BY127, BY133, BY227, 1N4006..07,+
1S460	Si-Di	SS, 22V, 0,045A, <3ns	31a	Fui	BA317, BAY71, BAY94, 1N4148..49,+
1S461	Si-Di	SS, 90V, 0,15A, <3ns	31a	Fui	BA219, 1N4148..49, 1N4446..49,+
1S462	Si-Di	SS, 90V, 0,22A, <3ns	31a	Fui	1N4148..49, 1N4151, 1N4446..49,+
1S463	Si-Di	S, 125V, 0,9A, <30ns	34	Fui	EGP10C, FE1C
1S464	Si-St	0,76..0,84V(10mA)	31a	Fui, Nec	BA220, BZ102/0V7, BZX55/C0V8, ZPD1
1S465	Si-Di	SS, 43V, 0,045A, <10ns	31a	Fui	BA218, BAX13, BAX91, 1N4148..49,+
1S466	Si-Di	SS, 43V, 0,045A, <1ns	31a	Fui	-
1S467	Si-St	Stabi, SS, 0,64..0,7V(3mA), <6ns	31a	Fui, Nec	BA220, BA315
1S468	Si-Di	SS, 50V, 0,115A, <3ns	31a	Fui	BA318, BAY38, 1N4148..49, 1N4151,+
1S47	Si-Di	=1S40: 800V	34a	Fui	BY127, BY133, BY227, 1N4006..07,+
1S470(H,L,M)	Z-Di	S, 5..6, 5V, 0,25W	31a	Fui	BZX55/.., BZX79/.., ZPD.., 1N5233..62,+
1S471(H,L,M)	Z-Di	=1S470: 6,5..8V	31a	-	-
1S472(H,L,M)	Z-Di	=1S470: 8..10V	31a	-	-
1S473(H,L,M)	Z-Di	=1S470: 10..12,5V	31a	-	-
1S474(H,L,M)	Z-Di	=1S470: 12,5..16V	31a	-	-
1S475(H,L,M)	Z-Di	=1S470: 16..20V	31a	-	-
1S476(H,L,M)	Z-Di	=1S470: 20..25V	31a	-	-
1S477(H,L,M)	Z-Di	=1S470: 25..31V	31a	-	-
1S478(H,L,M)	Z-Di	=1S470: 31..41V	31a	-	-
1S479(H,L,M)	Z-Di	=1S470: 41..51V	31a	-	-
1S48	Si-Di	FM/VHF-AFC, 20V, 13..28pF(10V)	31a	Tos	BA111, BA124, 1S2790, 1SV50,+
1S480(H,L,M)	Z-Di	S, 5,5..6,5V, 1W	34	Fui	BZW22/.., BZX61/.., ZPY.., 1N5919..41,+
1S481(H,L,M)	Z-Di	=1S480: 6,5..8V	34	-	-
1S482(H,L,M)	Z-Di	=1S480: 8..10V	34	-	-
1S483(H,L,M)	Z-Di	=1S480: 10..12,5V	34	-	-
1S484(H,L,M)	Z-Di	=1S480: 12,5..16V	34	-	-
1S485(H,L,M)	Z-Di	=1S480: 16..20V	34	-	-
1S486(H,L,M)	Z-Di	=1S480: 20..25V	34	-	-
1S487(H,L,M)	Z-Di	=1S480: 25..31V	34	-	-

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1S488(H,L,M)	Z-Di	=1S480:31..41V	34	-	-
1S489(H,L,M)	Z-Di	=1S480:41..51V	34	-	-
1S49	Si-Di	FM/VHF-AFC,20V,13..28pF(10V)	31a	Tos	BA111,BA124,1S2790,1SV50,+
1S490(H,L,M)	Z-Di	5,5..6,5V,3W	32a$	Fui	BZX98/..,,BZY93/..,ZX..,1N2970..97,+
1S491(H,L,M)	Z-Di	=1S490:6,5..8V	32a$	-	-
1S492(H,L,M)	Z-Di	=1S490:8..10V	32a$	-	-
1S493(H,L,M)	Z-Di	=1S490:10..12,5V	32a$	-	-
1S494(H,L,M)	Z-Di	=1S490:12,5..16V	32a$	-	-
1S495(H,L,M)	Z-Di	=1S490:16..20V	32a$	-	-
1S496(H,L,M)	Z-Di	=1S490:20..25V	32a$	-	-
1S497(H,L,M)	Z-Di	=1S490:25..31V	32a$	-	-
1S498(H,L,M)	Z-Di	=1S490:31..41V	32a$	-	-
1S499(H,L,M)	Z-Di	=1S490:41..51V	32a$	-	-
1S50	Ge-Di	Dem,40V,50mA	31a	Tos	AA113,AA119,1N34,1N54,1N60,+
1S500	Si-Di	SS,43V,0,045A,<3ns	31a	Fui	BA218,BAX13,BAX91,1N4148..49,+
1S501	Si-Di	SS,43V,0,075A,<3ns	31a	Fui	BA218,BAX13,BAX91,1N4148..49,+
1S5015(A)	Z-Di	15V,10W(Tc=100o),10%,(A=5%)	32b&	Tix	BZX98/..,BZY93/..,ZX..,1N2979..3011
1S5015C...5150C..	Z-Di	=1S5015..5150(A):bidirektional	32	-	-
1S5015C..5150C...	Z-Di	=1S5015..5150(A):Bidirectional	32	-	-
1S5015R...5150R..	Z-Di	=1S5015..5150(A):	32a$	-	-
1S5015R..5150R...	Z-Di	=1S5015..5150(A):	32a$	-	-
1S5016(A)	Z-Di	=1S5015(A):16V	32b&	-	-
1S5018(A)	Z-Di	=1S5015(A):18V	32b&	-	-
1S501M	Si-Di	=1S501:22V,0,045A,<1ns	31a	-	-
1S502...541	Ge-Di	-	2	Fui	-
1S502..541	Ge-Diode	-	2	Fuj	-
1S5020(A)	Z-Di	=1S5015(A):20V	32b&	-	-
1S5022(A)	Z-Di	=1S5015(A):22V	32b&	-	-
1S5024(A)	Z-Di	=1S5015(A):24V	32b&	-	-
1S5027(A)	Z-Di	=1S5015(A):27V	32b&	-	-
1S5030(A)	Z-Di	=1S5015(A):30V	32b&	-	-
1S5033(A)	Z-Di	=1S5015(A):33V	32b&	-	-
1S5036(A)	Z-Di	=1S5015(A):36V	32b&	-	-
1S5039(A)	Z-Di	=1S5015(A):39V	32b&	-	-
1S5043(A)	Z-Di	=1S5015(A):43V	32b&	-	-
1S5047(A)	Z-Di	=1S5015(A):47V	32b&	-	-
1S5051(A)	Z-Di	=1S5015(A):51V	32b&	-	-
1S5056(A)	Z-Di	=1S5015(A):56V	32b&	-	-
1S5062(A)	Z-Di	=1S5015(A):62V	32b&	-	-
1S5068(A)	Z-Di	=1S5015(A):68V	32b&	-	-
1S5075(A)	Z-Di	=1S5015(A):75V	32b&	-	-
1S5082(A)	Z-Di	=1S5015(A):82V	32b&	-	-
1S5091(A)	Z-Di	=1S5015(A):91V	32b&	-	-
1S51	Z-Di	3,8..4,5V	?34a	Tos	BZW22/..,BZX61/..,ZPY..,1N5915..25,+
1S5100(A)	Z-Di	=1S5015(A):100V	32b&	-	-
1S5110(A)	Z-Di	=1S5015(A):110V	32b&	-	-
1S5120(A)	Z-Di	=1S5015(A):120V	32b&	-	-
1S5130(A)	Z-Di	=1S5015(A):130V	32b&	-	-
1S5150(A)	Z-Di	=1S5015(A):150V	32b&	-	-
1S52	Z-Di	5,2..6,2V	?34a	-	-
1S53	Z-Di	6,0..7,1V	?34a	-	-
1S54	Z-Di	6,9..8,1V	?34a	-	-
1S542	Si-Di	Gl,Uni,500V,0,5A	31a	Tos	BY126..127,BY133..134,1N4005..07,+
1S543	Si-Di	UHF-M,720MHz,2V,20mA	-	Hit	-
1S544	Si-Di	Gl-L,800V,10A(Tc=120o)	32a$	Nec	BYX42/900,BYX98/900
1S545	Si-Di	=1S544:1000V	32a$	-	BYX42/1200,BYX98/1200
1S546	Si-Di	Gl-L,800V,20A(Tc=120o)	32a$	Nec	1N4528..30
1S547	Si-Di	=1S546:1000V	32a$	-	1N4528..30
1S548	Si-Di	SS,UHF,100V,0,1A,9GHz,<4ns	Koax	Oki	-
1S55	Z-Di	7,9..9,1V	?34a	-	-
1S550	Ref-Di	8..9V	2c	Nec	BZX51,1N4780
1S551	Ref-Di	8..9V	2c	-	BZX52,1N4781
1S552	Ref-Di	8..9V	2c	-	BZX53,1N4782
1S553(T)	C-Di	FM-AFC,30V,10..18pF(6V)	31a	Say	BA111,BA124,1S2790,1SV50,+

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1S554(T)	C-Di	=1S553(T): 16..21pF(6V)	31a	Say	BA111, BA124, 1S2790, 1SV50, +
1S555	C-Di	=1S553: 20..27pF(6V)	31a	Say	BA111, BA124, 1S2790, 1SV50, +
1S556	C-Di	=1S553: 23..40pF(6V)	31a	Say	BA111, BA124, 1S2790, 1SV50, +
1S557	Si-Di	Gl, Uni, 800V, 0,6A	12	Say	BY127, BY133, BY227, 1N4006..07, +
1S557H	Si-Di	=1S557: 1100V	12	-	BY127, BY133, BY227, GP10Q, +
1S558	Si-Di	=1S557: 500V	12	-	BY126..127, BY133..134, 1N4005..07, +
1S559	Si-Di	=1S557: 300V	12	-	BY126..127, BY133..134, 1N4004..07, +
1S56	Z-Di	8,9..10,1V	?34a	-	-
1S560(H)	Ge-Di	S, 15V, 0,04A, <200ns	31a	Hit	AAY27, 1N631, 1N633, 1N3592
1S561..569(A)	Ge-Di	-	31a	Njr	-
1S57	Si-Di	-	?34a	Tos	-
1S58	Ge-Br	4x Di, Br, 75V, 30mA	-	Tos	-
1S60	Si-Di	Gl, Uni, 50V, 0,75A	34	Son	BY126..127, BY133..135, 1N4001..07, +
1S6006(A)	Z-Di	6,8V, 10W(Tc=100o), 10%, (A=5%)	32b&	Tix	BZX98/.., BZY93/.., ZX.., 1N5921..56
1S6006R..6200R	Z-Di	=1S6006..6200(A):	32a&	-	-
1S6006R..6200R	Z-Di	=1S6006..6200(A): Reverse	32a&	-	-
1S6007(A)	Z-Di	=1S6006(A): 7,5V	32b&	-	-
1S6008(A)	Z-Di	=1S6006(A): 8,2V	32b&	-	-
1S6009(A)	Z-Di	=1S6006(A): 9,1V	32b&	-	-
1S6010(A)	Z-Di	=1S6006(A): 10V	32b&	-	-
1S6011(A)	Z-Di	=1S6006(A): 11V	32b&	-	-
1S6012(A)	Z-Di	=1S6006(A): 12V	32b&	-	-
1S6013(A)	Z-Di	=1S6006(A): 13V	32b&	-	-
1S6015(A)	Z-Di	=1S6006(A): 15V	32b&	-	-
1S6016(A)	Z-Di	=1S6006(A): 16V	32b&	-	-
1S6018(A)	Z-Di	=1S6006(A): 18V	32b&	-	-
1S6020(A)	Z-Di	=1S6006(A): 20V	32b&	-	-
1S6022(A)	Z-Di	=1S6006(A): 22V	32b&	-	-
1S6024(A)	Z-Di	=1S6006(A): 24V	32b&	-	-
1S6027(A)	Z-Di	=1S6006(A): 27V	32b&	-	-
1S6030(A)	Z-Di	=1S6006(A): 30V	32b&	-	-
1S6033(A)	Z-Di	=1S6006(A): 33V	32b&	-	-
1S6036(A)	Z-Di	=1S6006(A): 36V	32b&	-	-
1S6039(A)	Z-Di	=1S6006(A): 39V	32b&	-	-
1S6043(A)	Z-Di	=1S6006(A): 43V	32b&	-	-
1S6047(A)	Z-Di	=1S6006(A): 47V	32b&	-	-
1S6051(A)	Z-Di	=1S6006(A): 51V	32b&	-	-
1S6056(A)	Z-Di	=1S6006(A): 56V	32b&	-	-
1S6062(A)	Z-Di	=1S6006(A): 62V	32b&	-	-
1S6068(A)	Z-Di	=1S6006(A): 68V	32b&	-	-
1S6075(A)	Z-Di	=1S6006(A): 75V	32b&	-	-
1S6082(A)	Z-Di	=1S6006(A): 82V	32b&	-	-
1S6091(A)	Z-Di	=1S6006(A): 91V	32b&	-	-
1S61	Si-Di	=1S60: 100V	34	-	BY126..127, BY133..135, 1N4001..07, +
1S6100(A)	Z-Di	=1S6006(A): 100V	32b&	-	-
1S611	Z-Di	2..3,2V, 0,2W	2c	Khe	BZX55/.., BZX79/.., ZPD.., 1N5221..37, +
1S6110(A)	Z-Di	=1S6006(A): 110V	32b&	-	-
1S612	Z-Di	=1S611: 3..3,9V	2c	-	-
1S6120(A)	Z-Di	=1S6006(A): 120V	32b&	-	-
1S613	Z-Di	=1S611: 3,7..4,5V	2c	-	-
1S6130(A)	Z-Di	=1S6006(A): 130V	32b&	-	-
1S614	Z-Di	=1S611: 4,3..5,4V	2c	-	-
1S615	Z-Di	=1S611: 5,2..6,4V	2c	-	-
1S6150(A)	Z-Di	=1S6006(A): 150V	32b&	-	-
1S616	Z-Di	=1S611: 6,2..8V	2c	-	-
1S6160(A)	Z-Di	=1S6006(A): 160V	32b&	-	-
1S617	Z-Di	7,5..10V, 0,15W	2c	Khe	BZX55/.., BZX79/.., ZPD.., 1N5236..59, +
1S618	Z-Di	=1S617: 9..12V	2c	-	-
1S6180(A)	Z-Di	=1S6006(A): 180V	32b&	-	-
1S619	Z-Di	=1S617: 11..14,5V	2c	-	-
1S62	Si-Di	=1S60: 200V	34	-	BY126..127, BY133..134, 1N4002..07, +
1S620	Z-Di	=1S617: 13,5..18V	2c	-	-
1S6200(A)	Z-Di	=1S6006(A): 200V	32b&	-	-
1S621	Z-Di	=1S617: 17..21V	2c	-	-

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1S622	Z-Di	=1S617:20..27V	2c	-	-
1S623	Z-Di	=1S617:25..32V	2c	-	-
1S624	Z-Di	=1S617:30..39V	2c	-	-
1S63	Si-Di	=1S60:300V	34	-	BY126..127,BY133..134,1N4003..07,+
1S632	Z-Di	3..3,9V,0,2W	2c	Khe	BZX55/..,BZX79/..,ZPD..,1N5225..37,+
1S633	Z-Di	=1S632:3,7..4,5V	2c	-	-
1S634	Z-Di	=1S632:4,3..5,4V	2c	-	-
1S635	Z-Di	=1S632:5,2..6,4V	2c	-	-
1S636	Z-Di	=1S632:6,2..8V	2c	-	-
1S64	Si-Di	=1S60:400V	34	-	BY126..127,BY133..134,1N4004..07,+
1S65	Si-Di	=1S60:500V	34	-	BY126..127,BY133..134,1N4005..07,+
1S66	Si-Di	=1S60:600V	34	-	BY126..127,BY133..134,1N4005..07,+
1S661	Si-Di	GI,400V,1A(Tc=120o)	34	Fjd	BY252..255,BYW17/400,1N5404..08,+
1S662	Si-Di	=1S661:800V	34	-	BY254..255,BYW17/800,1N5407..08,+
1S663	Si-Di	=1S661:1000V	34	-	BY255,BY228,BYW17/1000,1N5408,+
1S664	Si-Di	=1S661:1200V	34	-	BY255,BY228,BYW17/1200
1S665	Si-Di	GI-L,400V,2,5A(Tc=120o)	?32b&	Fjd	BYX38/600R,BYX39/600R
1S666	Si-Di	=1S665:800V	?32b&	-	BYX38/900R,BYX39/900R
1S667	Si-Di	=1S665:1000V	?32b&	-	BYX38/1200R,BYX39/1000R
1S668	Si-Di	=1S665:1200V	?32b&	-	BYX38/1200R,BYX39/1200R
1S669	Si-Di	GI-L,400V,10A(Tc=120o)	73b&	Fjd	BYX42/600R,BYX98/600R
1S670	Si-Di	=1S669:800V	73b&	-	BYX42/900R,BYX98/900R
1S671	Si-Di	=1S669:1000V	73b&	-	BYX42/1200R,BYX98/1200R
1S672	Si-Di	=1S669:1200V	73b&	-	BYX42/1200R,BYX98/1200R
1S673	Si-Di	GI-L,400V,20A(Tc=120o)	73b&	Fjd	BYX56/600R,BYX97/600R
1S674	Si-Di	=1S673:800V	73b&	-	BYX56/800R,BYX97/900R
1S675	Si-Di	=1S673:1000V	73b&	-	BYX56/1000R,BYX97/1200R
1S676	Si-Di	=1S673:1200V	73b&	-	BYX56/1200R,BYX97/1200R
1S677	Si-Di	GI-L,400V,82,5A(Tc=105o)	73b&	Fjd	1N3291R..97R
1S678	Si-Di	=1S677:800V	73b&	-	1N3294R..97R
1S679	Si-Di	=1S677:1000V	73b&	-	1N3295R..97R
1S680	Si-Di	=1S677:1200V	73b&	-	1N3296R..97R
1S681	Si-Di	GI-L,400V,200A(Tc=105o)	73b&	Fjd	1N3738R..44R
1S682	Si-Di	=1S681:800V	73b&	-	1N3741R..44R
1S683	Si-Di	=1S681:1000V	73b&	-	1N3742R..44R
1S684	Si-Di	=1S681:1200V	73b&	-	1N3743R..44R
1S685	Si-Di	GI,300V,0,35A	31a	Gie	BA157..159,BY204/4,BY206..207,+
1S686	Si-Di	=1S685:450V	31a	-	BA158..159,BY204/8,BY207,+
1S687	Si-Di	=1S685:750V	31a	-	BA158..159,BY204/8,BY268..269,+
1S688	Si-Di	=1S685:1200V	31a	-	BY127,BY133,BY227,BY268..269,+
1S689(A)	Ge-Di	TV-Damper-Di,200..270V,6A(Tc=50o)	22	Hit	-
1S690	Z-Di	3,6..4,3,1W	34	Inr	BZW22/..,BZX61/..,ZPY..,1N5914..36,+
1S691	Z-Di	=1S690:4,3..5,1V	34	-	-
1S692	Z-Di	=1S690:5,1..6,2V	34	-	-
1S693	Z-Di	=1S690:6,2..7,5V	34	-	-
1S694	Z-Di	=1S690:7,5..9,1V	34	-	-
1S695	Z-Di	=1S690:9,1..11V	34	-	-
1S696	Z-Di	=1S690:11..13V	34	-	-
1S697	Z-Di	=1S690:13..16V	34	-	-
1S698	Z-Di	=1S690:16..20V	34	-	-
1S699	Z-Di	=1S690:20..24V	34	-	-
1S700	Z-Di	=1S690:24..30V	34	-	-
1S700P	Si-Di	TV	-		(BY329/1000,BY359/1000,BYW19/1000,++)
1S701	Z-Di	3,6..4,3V,3,5W	32	Inr	BZX98/..,BZY93/..,ZX..,1N2970..89,+
1S702	Z-Di	=1S701:4,3..5,1V	32	-	-
1S703	Z-Di	=1S701:5,1..6,2V	32	-	-
1S7030(A,B)	Z-Di	3V,0,4W,10%,(A=5%,B=15%)	31a	Tix	BZX55/..,BZX83/..,ZPD..,1N5225..46,+
1S7033(A,B)	Z-Di	=1S7030(A,B):3,3V	31a	-	-
1S7036(A,B)	Z-Di	=1S7030(A,B):3,6V	31a	-	-
1S7039(A,B)	Z-Di	=1S7030(A,B):3,9V	31a	-	-
1S704	Z-Di	=1S701:6,2..7,5V	32	-	-
1S7043(A,B)	Z-Di	=1S7030(A,B):4,3V	31a	-	-
1S7047(A,B)	Z-Di	=1S7030(A,B):4,7V	31a	-	-
1S705	Z-Di	=1S701:7,5..9,1V	32	-	-

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1S7051(A,B)	Z-Di	=1S7030(A,B):5,1V	31a	-	-
1S7056(A,B)	Z-Di	=1S7030(A,B):5,6V	31a	-	-
1S706	Z-Di	=1S701:9,1..11V	32	-	-
1S7062(A,B)	Z-Di	=1S7030(A,B):6,2V	31a	-	-
1S7068(A,B)	Z-Di	=1S7030(A,B):6,8V	31a	-	-
1S707	Z-Di	=1S701:11..13V	32	-	-
1S7075(A,B)	Z-Di	=1S7030(A,B):7,5V	31a	-	-
1S708	Z-Di	=1S701:13..16V	32	-	-
1S7082(A,B)	Z-Di	=1S7030(A,B):8,2V	31a	-	-
1S709	Z-Di	=1S701:16..20V	32	-	-
1S7091(A,B)	Z-Di	=1S7030(A,B):9,1V	31a	-	-
1S71	Si-Di	Uni,175V,0,06A	31a	Tos	BA147/230,BA190,1N5195..96,+
1S710	Z-Di	=1S701:20..24V	32	-	-
1S7100(A,B)	Z-Di	=1S7030(A,B):10V	31a	-	-
1S711	Z-Di	=1S701:24..30V	32	-	-
1S7110(A,B)	Z-Di	=1S7030(A,B):11V	31a	-	-
1S712	Z-Di	3,6..4,3V,10W	32	Inr	BZX98/..,BZY93/..,ZX..,1N2970..89,+
1S7120(A,B)	Z-Di	=1S7030(A,B):12V	31a	-	-
1S713	Z-Di	=1S712:4,3..5,1V	32	-	-
1S7130(A,B)	Z-Di	=1S7030(A,B):13V	31a	-	-
1S714	Z-Di	=1S712:5,1..6,2V	32	-	-
1S715	Z-Di	=1S712:6,2..7,5V	32	-	-
1S7150(A,B)	Z-Di	=1S7030(A,B):15V	31a	-	-
1S716	Z-Di	=1S712:7,5..9,1V	32	-	-
1S7160(A,B)	Z-Di	=1S7030(A,B):16V	31a	-	-
1S717	Z-Di	=1S712:9,1..11V	32	-	-
1S718	Z-Di	=1S712:11..13V	32	-	-
1S719	Z-Di	=1S712:13..16V	32	-	-
1S72	Si-Di	=1S71:130V	31a	Tos	BA147/150,BA189..190,1N5195..96,+
1S720	Z-Di	=1S712:16..20V	32	-	-
1S721	Z-Di	=1S712:20..24V	32	-	-
1S722	Z-Di	=1S712:24..30V	32	-	-
1S723	Si-Di	Gl-L,400V,6A(Tc=105o)	32	Inr	BYX38/600,BYX39/600
1S724	Si-Di	=1S723:600V	32	-	BYX38/600,BYX39/600
1S725	Si-Di	=1S723:800V	32	-	BYX38/900,BYX39/800
1S726	Si-Di	=1S723:1000V	32	-	BYX38/1200,BYX39/1000
1S73(A)	Ge-Di	S,20(A=30)V,0,12A,<900ns	31a	Tos	AAY49,AAZ15,AAZ17
1S731	Si-Di	SS,50V,0,1A,<4ns	31a	Nec	BA318,BAY38,1N4148..49,1N4151,+
1S732	Si-Di	Gl-L,200V,250A(Tc=105o)	73a$	Nec	1N3736..44
1S733	Si-Di	=1S732:300V	73a$	-	1N3737..44
1S734	Si-Di	=1S732:400V	73a$	-	1N3738..44
1S735	Si-Di	=1S732:500V	73a$	-	1N3739..44
1S736	Si-Di	=1S732:600V	73a$	-	1N3740..44
1S737	Si-Di	=1S732:700V	73a$	-	1N3741..44
1S738	Si-Di	=1S732:800V	73a$	-	1N3741..44
1S739	Si-Di	=1S732:900V	73a$	-	1N3742..44
1S74	Ge-Di	Uni,75V,50mA	31a	Njr,Son	AA117..118,AA132..133
1S740	Si-Di	=1S732:1000V	73a$	-	1N3742..44
1S741	Si-Di	=1S732:100V	73a$	-	1N3735..44
1S742	Si-Di	=1S732:1200V	73a$	-	1N3743..44
1S743	Si-Di	=1S732:1500V	73a$	-	-
1S744	Ge-Di	Dem,40V,40mA	31a	Oki	AA113,AA119,1N34,1N54,1N60
1S745	Ge-Di	Dem,50V,65mA	31a	Oki	AA113,1N34,1N54,1N60
1S746	Ge-Di	Dem,75V,45mA	31a	Oki	AA113,1N34,1N54,1N60
1S747	Ge-Di	Dem,75V,45mA	31a	Oki	AA113,1N34,1N54,1N60
1S748	Ge-Di	Dem,20V,40mA	31a	Oki	AA112..114,1N34,1N54,1N60,+
1S75	Ge-Di	Uni,30V,25mA	31a	Njr,Son	AA117..118,AA132..134,1N34,1N54,+
1S750(S)	Si-Di	UHF-M,887MHz,2V,20mA	31a	Hit	-
1S751	Ge-Di	TV-Damper-Di,200V,5A	22	Fui	-
1S752(S)	Z-Di	2..3,2V,0,25W	2	Hit	BZX55/..,BZX79/..,ZPD..,1N5221..59,+
1S753(S)	Z-Di	=1S752:3..3,9V	2	-	-
1S754(S)	Z-Di	=1S752:3,7..4,5V	2	-	-
1S755(S)	Z-Di	=1S752:4,3..5,4V	2	-	-
1S756(S)	Z-Di	=1S752:5,2..6,4V	2	-	-

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1S757(S)	Z-Di	=1S752:6,2..8V	2	-	-
1S758(S)	Z-Di	=1S752:7,5..10V	2	-	-
1S759(S)	Z-Di	=1S752:9..12V	2	-	-
1S76	Ge-Di	Dem,45V,50mA	31a	Njr,Son	AA113,AA119,1N34,1N54,1N60
1S760(S)	Z-Di	=1S752:11..14,5V	2	-	-
1S761(S)	Z-Di	=1S752:13,5..18V	2	-	-
1S762(S)	Z-Di	=1S752:17..21V	2	-	-
1S763(S)	Z-Di	=1S752:20..27V	2	-	-
1S764(S)	Z-Di	=1S752:25..32V	2	-	-
1S765(S)	Z-Di	=1S752:30..39V	2	-	-
1S766...769	Si-Di	HF-Multiplier	-	Oki	-
1S766..769	SI-Di	-		Oki	-
1S77(H)	Ge-Di	S,60V,60mA,H:400ns	31a	Hit	AA117..118,AA132..133,AAY28
1S770	Si-Di	GI-L,100V,1SA(Tc=50o)	7Sa	Tos	1N3492..9S
1S770R	Si-Di	=1S770:	7Sb	-	1N3492R..9SR
1S773(A)	SI-Di	SS,35V,0,1A,<4ns	2a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S774(A)	Si-Di	SS,35V,0,12A,<4ns	2a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S775(A)	Si-Di	SS,80V,0,08A,<3ns	2a	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S776(A)	Si-Di	SS,130V,0,1A,<3ns	2a	Oki	-
1S777	Ge-Di	TV-Damper-Di,200V,3A	22	Tos	-
1S778	Si-Di	GI-L,100V,12A(Tc=40o)	32a	Inr	BYW88/100,BYX76..81
1S779	SI-Di	GI-L,150V,40A(Tc=104o)	32b	Inr	BYX56/600R,BYX97/300R
1S78(H)	Ge-Di	S,40V,80mA,H:400ns	31a	Hit	AA117..118,AA132..133,AAY49
1S780	Si-Di	=1S779:200V	32b	-	BYX56/600R,BYX97/300R
1S781	Si-Di	=1S778:250V	32a	-	BYW88/300,BYX78..81
1S782	Si-Di	=1S779:300V	32b	-	BYX56/600R,BYX97/300R
1S783	Si-Di	=1S779:400V	32b	-	BYX56/600R,BYX97/600R
1S784	Si-Di	=1S779:500V	32b	-	BYX56/600R,BYX97/600R
1S785	Si-Di	=1S779:600V	32b	-	BYX56/600R,BYX97/600R
1S786	SI-Di	=1S779:800V	32b	-	BYX56/800R,BYX97/900R
1S787	Si-Di	GI-L,100V,60A(Tc=126o)	32b	Inr	-
1S788	Si-Di	=1S787:150V	32b	-	-
1S789	Si-Di	=1S787:200V	32b	-	-
1S79(H)	Ge-Di	S,20V,0,1A,H:400ns	31a	Hit	AA117..118,AA132..133,AAY49
1S790	Si-Di	GI-L,250V,18A(Tc=40o)	32a	Inr	-
1S791	Si-Di	=1S787:300V	32b	-	-
1S792	Si-Di	=1S787:400V	32b	-	-
1S793	Si-Di	=1S787:500V	32b	-	-
1S794	Si-Di	=1S787:600V	32b	-	-
1S795	SI-Di	=1S787:800V	32b	-	-
1S796(N)	Z-Di	75V,5%,50W(Tc=55o)	23	Tos	-
1S797(N)	Z-Di	=1S796:95V	23	-	-
1S798(N)	Z-Di	=1S796:105V	23	-	-
1S799(N)	Z-Di	=1S796:150V	23	-	-
1S80	Ge-Di	Dem,30V,40mA	31a	Hit	AA113,AA119,1N34,1N54,1N60,+
1S800(N)	Z-Di	=1S796:180V	23	-	-
1S801	Si-Di	Min,SS,22V,0,055A,<4ns	31a	Oki	(BA217,BA317,BAY71,1N4148..49,++)
1S802	Si-Di	Min,SS,30V,0,06A,<4ns	31a	Oki	(BA217,BA317,BAY71,1N4148..49,++)
1S803	Si-Di	Min,SS,30V,0,065A,<4ns	31a	Oki	(BA217,BA317,BAY71,1N4148..49,++)
1S804	SI-Di	Min,SS,50V,0,06A,<4ns	31a	Oki	(BA218,BA318,BAY38,1N4148..49,++)
1S805	Si-Di	Min,SS,50V,0,065A,<2ns	31a	Oki	(BA218,BA318,BAY38,1N4148..49,++)
1S806	SI-Di	Min,SS,50V,0,065A,<2ns	31a	Oki	(BA218,BA318,BAY38,1N4148..49,++)
1S807	Si-Di	Min,SS,75V,0,065A,<2ns	31a	Oki	(BAW62,BAX95,BAW76,1N4148..49,++)
1S808	Si-Di	Min,SS,100V,0,065A,<2ns	31a	Oki	(BA219,BAX96,1N4148..49,1N4151,++)
1S81	Si-Di	Uni,230V,0,06A	31a	Tos	BA147/230,BA157..1S9,BAY21,+
1S810	Ge-Di	Uni,100V,0,1A	31a	Tos	AA117..118,AA132..133,1N634..35
1S811	Si-Di	GI,Uni,250V,0,5A(Tc=100o)	31a	Fjd	BY126..127,BY133..134,1N4004..07,+
1S812	Si-Di	=1S811:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S813	Si-Di	=1S811:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S814	SI-Di	=1S811:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S815	Si-Di	=1S811:1200V	31a	-	BY127,BY133,BY227,GP10Q,+
1S816	Si-Di	GI,Uni,250V,1A(Tc=120o)	34	Fjd	BY252..255,BYW17/400,1N5404..08,+
1S817	SI-Di	=1S816:400V	34	-	BY252..255,BYW17/400,1N5404..08,+
1S818	Si-Di	=1S816:800V	34	-	BY254..255,BYW17/800,1N5407..08,+

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1S819	Si-Di	=1S816: 1000V	34	-	BY228, BY255, BYW17/1000, 1N5408, +
1S82	Ge-Di	Uni, 50V, 50mA	31a	Tos	AA117..118, AA132..134, 1N34, 1N54, +
1S820	Si-Di	=1S816: 1200V	34	-	BY228, BY255, BYW17/1200, +
1S821	Si-Di	GI-L, 250V, 2,5A(Tc=120o)	?32b&	Fjd	BYX38/300R, BYX39/600R
1S822	Si-Di	=1S821: 400V	?32b&	-	BYX38/600R, BYX39/600R
1S823	Si-Di	=1S821: 800V	?32b&	-	BYX38/900R, BYX39/800R
1S824	Si-Di	=1S821: 1000V	?32b&	-	BYX38/1200R, BYX39/1000R
1S825	Si-Di	=1S821: 1200V	?32b&	-	BYX38/1200R, BYX39/1200R
1S826	Si-Di	GI-L, 250V, 6A(Tc=120o)	73b&	Fjd	BYX38/300R, BYX39/600R
1S827	Si-Di	=1S826: 400V	73b&	-	BYX38/600R, BYX39/600R
1S828	Si-Di	=1S826: 800V	73b&	-	BYX38/900R, BYX39/800R
1S829	Si-Di	=1S826: 1000V	73b&	-	BYX38/1200R, BYX39/1000R
1S83(H)	Ge-Di	GI, Uni, 80V, 0,2A	2	Hit	1N270
1S830	Si-Di	=1S826: 1200V	73b&	-	BYX38/1200R, BYX39/1200R
1S831	Si-Di	GI-L, 250V, 10A(120o)	73b&	Fjd	BYX42/300R, BYX98/300R
1S832	Si-Di	=1S831: 400V	73b&	-	BYX42/600R, BYX98/600R
1S833	Si-Di	=1S831: 800V	73b&	-	BYX42/900R, BYX98/900R
1S834	Si-Di	=1S831: 1000V	73b&	-	BYX42/1200R, BYX98/1200R
1S835	Si-Di	=1S831: 1200V	73b&	-	BYX42/1200R, BYX98/1200R
1S836	Si-Di	GI-L, 250V, 20A(Tc=120o)	73b&	Fjd	D24/400B
1S837	Si-Di	=1S836: 400V	73b&	-	D24/400B
1S838	Si-Di	=1S836: 800V	73b&	-	D24/800B
1S839	Si-Di	=1S836: 1000V	73b&	-	D24/1000B
1S84(H)	Ge-Di	GI, S, 200V, 0,1A, H: 15?s	2	Hit	1N39
1S840	Si-Di	=1S836: 1200V	73b&	-	D24/1200B
1S841	Si-Di	GI, Uni, 100V, 1A	34a$	Nec	BY126..127, BY133..134, 1N4002..07, +
1S842	Si-Di	=1S841: 200V	34a$	-	BY126..127, BY133..134, 1N4003..07, +
1S843	Si-Di	=1S841: 300V	34a$	-	BY126..127, BY133..134, 1N4004..07, +
1S844(N)	Si-Di	=1S841: 400V	34a$	Nec, Fjd, Shi	BY126..127, BY133..134, 1N4004..07, +
1S845	Si-Di	=1S841: 500V	34a$	-	BY126..127, BY133..134, 1N4005..07, +
1S846(N)	Si-Di	=1S841: 600V	34a$	Nec, Fjd, Shi	BY126..127, BY133..134, 1N4005..07, +
1S847	Si-Di	=1S841: 700V	34a$	-	BY127, BY133, BY227, 1N4006..07, +
1S848(N)	Si-Di	=1S841: 800V	34a$	Nec, Fjd, Shi	BY127, BY133, BY227, 1N4006..07, +
1S849	Si-Di	=1S841: 900V	34a$	-	BY127, BY133, BY227, 1N4007, +
1S85(H)	C-Di	AFC, 20(H=30)V, 14..26pF(10V)	31a	Hit	BA124..125, BB119, 1S2790, 1SV50, +
1S850(N)	Si-Di	=1S841: 1000V	34a$	Nec, Fjd, Shi	BY127, BY133, BY227, 1N4007, +
1S851	Si-Di	=1S841: 1200V	34a$	-	BY127, BY133, BY227, GP10Q, +
1S852	Si-Di	=1S841: 1500V	34a$	-	BY350/1500, BY400, BY448, GP10W
1S853	Si-Di	GI, 300V, 2,5A	-	Sak	(BY205/400, BY229/400, BYX49/300, ++)
1S854	Si-Di	=1S853: 400V	-		(BY205/400, BY229/400, BYX49/600, ++)
1S855	Si-Di	=1S853: 500V	-		(BY205/600, BY229/600, BYX49/600, ++)
1S856	Si-Di	=1S853: 600V	-		(BY205/600, BY229/600, BYX49/600, ++)
1S857	Si-Di	=1S853: 700V	-		(BY205/800, BY229/800, BYX49/900, ++)
1S858	Si-Di	=1S853: 800V	-		(BY205/800, BY229/800, BYX49/900, ++)
1S859	Si-Di	=1S853: 900V	-		(BY205/1000, BY229/1000, BYX49/1200, ++)
1S86	C-Di	FM/VHF-AFC, 20V, 10..18pF(10V)	31a	Tos	BA124..125, BB119, 1S2790, 1SV50, +
1S860	Si-Di	=1S853: 1000V	-		(BY205/1000, BY229/1000, BYX49/1200, ++)
1S861	Si-Di	GI-L, 100V, 10A(Tc=40o)	75a$	Sak	1N3492..95
1S861R	Si-Di	=1S861:	75b&	-	1N3492R..95R
1S863	Si-Di	GI-L, 300V, 8A	73a$	Sak	BYX42/300, BYX98/300
1S864	Si-Di	=1S863: 400V	73a$	-	BYX42/600, BYX98/600
1S865	Si-Di	=1S863: 500V	73a$	-	BYX42/600, BYX98/600
1S866	Si-Di	=1S863: 600V	73a$	-	BYX42/600, BYX98/600
1S867	Si-Di	=1S863: 700V	73a$	-	BYX42/900, BYX98/900
1S868	Si-Di	=1S863: 800V	73a$	-	BYX42/900, BYX98/900
1S869	Si-Di	=1S863: 900V	73a$	-	BYX42/900, BYX98/900
1S87	Ge-Di	S, 20V, 0,1A, <120ns	31a	Tos	AAY49, AAZ15, AAZ17
1S870	Si-Di	=1S863: 1000V	73a$	-	BYX42/1200, BYX98/1200
1S871	Si-Di	GI, Uni, 400V, 0,15A	31a	Sak	BA157..159, BY203/12, BY204/4, +
1S871A	Si-Di	=1S871: 600V	31a	-	BA158..159, BY203/12, BY204/8, +
1S871B	Si-Di	=1S871: 800V	31a	-	BA158..159, BY203/12, BY204/8, +
1S871C	Si-Di	=1S871: 1000V	31a	-	BA159, BAY90, BY203/12, BY204/10, +
1S871D	Si-Di	=1S871: 1200V	31a	-	BAY91, BY203/12, SHG1,5
1S871E	Si-Di	=1S871: 1400V	31a	-	BAY91, BY203/16, SHG1,5

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1S871F	Si-Di	=1S871:1600V	31a	-	BAY91,BY203/16,SHG2
1S871G	Si-Di	=1S871:1800V	31a	-	BAY91,BY203/20,SHG2
1S871H	Si-Di	=1S871:2000V	31a	-	BAY91,BY203/20,SHG2
1S872	Si-Di	Gl,Uni,400V,0,25A	31a	Sak	BA157..159,BY204/4,BY203/12,+
1S872A	Si-Di	=1S872:600V	31a	-	BA158..159,BY204/8,BY203/12,+
1S872B	Si-Di	=1S872:800V	31a	-	BA158..159,BY204/8,BY203/12,+
1S872C	Si-Di	=1S872:1000V	31a	-	BA159,BAY90,BY204/10,BY203/12,+
1S872D	Si-Di	=1S872:1200V	31a	-	BAY91,BY203/12,BY268..269,+
1S873	Si-Di	Gl-L,300V,17A	73a$	Sak	BYX96/300
1S874	Si-Di	=1S873:400V	73a$	-	BYX96/600
1S875	Si-Di	=1S873:500V	73a$	-	BYX96/600
1S876	Si-Di	=1S873:600V	73a$	-	BYX96/600
1S877	Si-Di	=1S873:700V	73a$	-	BYX96/900
1S878	Si-Di	=1S873:800V	73a$	-	BYX96/900
1S879	Si-Di	=1S873:900V	73a$	-	BYX96/900
1S88	Ge-Di	=1S87:<240ns	31a	Tos	AAY49,AAZ15,AAZ17
1S880	Si-Di	=1S873:1000V	73a$	-	BYX96/1200
1S881	Si-Di	Gl,Uni,400V,0,5A	31a	Sak	BY126..127,BY133..134,1N4004..07,+
1S881A	Si-Di	=1S881:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S881B	Si-Di	=1S881:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S881C	Si-Di	=1S881:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S881D	Si-Di	=1S881:1200V	31a	-	BY127,BY133,BY227,BY268..269,+
1S881E	Si-Di	=1S881:1400V	31a	-	BY268..269,GP10V,DM513,EM516,+
1S882	Si-Di	Gl,Uni,400V,0,75A	31a	Sak	BY126..127,BY133..134,1N4004..07,+
1S882A	Si-Di	=1S882:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S882B	Si-Di	=1S882:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S882C	Si-Di	=1S882:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S882D	Si-Di	=1S882:1200V	31a	-	BY127,BY133,BY227,BY268..269,+
1S882E	Si-Di	=1S882:1400V	31a	-	BY268..269,GP10V,DM513,EM516,+
1S883	Si-Di	Gl-L,300V,100A	73a$	Sak	1N3290..97
1S884	Si-Di	=1S883:400V	73a$	-	1N3291..97
1S885	Si-Di	=1S883:500V	73a$	-	1N3292..97
1S886	Si-Di	=1S883:600V	73a$	-	1N3293..97
1S887	Si-Di	=1S883:700V	73a$	-	1N3294..97
1S888	Si-Di	=1S883:800V	73a$	-	1N3294..97
1S889	Si-Di	=1S883:900V	73a$	-	1N3295..97
1S89	Ge-Di	=1S87:<340ns	31a	Tos	AAY49,AAZ15,AAZ17
1S890	Si-Di	=1S883:1000V	73a$	-	1N3295..97
1S891	C-Di	AFC,35V,10<12pF(10V)	31a	Sak	BA124..125,BB119,1S2790,1SV50,+
1S892	C-Di	AFC,25V,12..18pF(10V)	31a	Sak	BA124..125,BB119,1S2790,1SV50,+
1S893	C-Di	AFC,25V,16..24pF(10V)	31a	Sak	BA124..125,BB119,1S2790,1SV50,+
1S894	Si-Di	kV-Gl,6kV,0,03A	31a	Sak	CY7,HS6
1S895	Si-Di	=1S894:8kV	31a	-	CY10,HS8
1S896	Si-Di	=1S894:10kV	31a	-	CY10,HS8
1S897	Si-Di	=1S894:12kV	31a	-	HS10
1S90	Si-Di	Gl,150V,0,3A	34a$	Tos	BY126..127,BY133..135,1N4003..07,+
1S90R..99R	Si-Di	=1S90..99:	34b&	-	→1S90..99
1S91	Si-Di	=1S90:200V	34a$	-	BY126..127,BY133..134,1N4003..07,+
1S92	Si-Di	=1S90:300V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S920	Si-Di	-	31a	Fch,Tix	BA187
1S920[Fch,Tix]	Si-Di	=BA187	31a	Fch,Tix	→BA187
1S921	Si-Di	-	34	Shindengen	BY226..227,BY251..255,1N5393..99,+
1S921[Fch,Tix]	Si-Di	=BA188	31a	Fch,Tix	→BA188
1S921[Japan]	Si-Di	Gl,Uni,200V,1,5A	34	Shi	BY226..227,BY251..255,1N5393..99,+
1S922[Fch,Tix]	Si-Di	=BA189	31a	Fch,Tix	→BA189
1S922[Japan]	Si-Di	=1S921[Japan]:400V	34	Shi	BY226..227,BY252..255,1N5395..99,+
1S923[Fch,Tix]	Si-Di	=BA190	31a	Fch,Tix	→BA190
1S923[Japan]	Si-Di	=1S921[Japan]:600V	34	Shi	BY226..227,BY253..255,1N5397..99,+
1S924	Si-Di	-	34	Shindengen	BY227,BY254..255,1N5398..99..
1S924[Japan]	Si-Di	=1S921[Japan]:800V	34	Shi	BY227,BY254..255,1N5398..99,+
1S925	Si-Di	-	34	-	BY227,BY255,BYX86..87,1N5399..
1S925[Japan]	Si-Di	=1S921[Japan]:1000V	34	-	BY227,BY255,BYX86..87,1N5399,+
1S926	Si-Di	Gl-L,200V,20A(Tc=90o)	73a$	Shi	1N4525..30
1S927	Si-Di	=1S926:400V	73a$	-	1N4526..30

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1S928	Si-Di	=1S926:600V	73a$	-	1N4527..30
1S929	Si-Di	=1S926:800V	73a$	-	1N4528..30
1S93	Si-Di	=1S90:400V	34a$	-	BY126..127,BY133..134,1N4004..07,+
1S930	Si-Di	=1S926:1000V	73a$	-	1N4529..30
1S931	Si-Di	GI-L,200V,50A(Tc=79o)	73a$	Shi	1N3289..97
1S932	Si-Di	=1S931:400V	73a$	-	1N3291..97
1S933	Si-Di	=1S931:600V	73a$	-	1N3293..97
1S934	Si-Di	=1S931:800V	73a$	-	1N3294..97
1S935	Si-Di	=1S931:1000V	73a$	-	1N3295..97
1S936	Si-Di	-	73a$	Shi	1N3289..97
1S936[Japan]	Si-Di	GI-L,200V,100A(Tc=91o)	73a$	Shi	1N3289..97
1S937	Si-Di	-	73a$	-	1N3291..97
1S937[Japan]	Si-Di	=1S936[Japan]:400V	73a$	-	1N3291..97
1S938	Si-Di	-	73a$	-	1N3293..97
1S938[Japan]	Si-Di	=1S936[Japan]:600V	73a$	-	1N3293..97
1S939	Si-Di	-	73a$	-	1N3294..97
1S939[Japan]	Si-Di	=1S936[Japan]:800V	73a$	-	1N3294..97
1S94	Si-Di	=1S90:500V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S940	Si-Di	-	31a	TI	BA147/50,BA187..190,1N5606..09,+
1S940[Japan]	Si-Di	=1S936[Japan]:1000V	73a$	-	1N3295..97
1S940[Texas]	Si-Di	Uni,30V,0,05A	31a	Tix	BA147/50,BA187..190,1N5606..09,+
1S941	Si-Di	-		Shi	-
1S941[Japan]	Si-Di	GI-L,200V,200A(Tc=83o)	-	Shi	-
1S941[Texas]	Si-Di	=1S940[Texas]:50V	31a	Tix	BA147/50,BA187..190,1N5606..09,+
1S942	Si-Di	-	31a	TI	BA147/100,BA188..190,1N5606..09,+
1S942[Japan]	Si-Di	=1S941[Japan]:400V	-	Shi	-
1S942[Texas]	Si-Di	=1S940[Texas]:75V	31a	Tix	BA147/100,BA188..190,1N5606..09,+
1S943	Si-Di	-		Shi	-
1S943[Japan]	Si-Di	=1S941[Japan]:600V	-	Shi	-
1S944	Si-Di	-		-	-
1S944[Japan]	Si-Di	=1S941[Japan]:800V	-		-
1S945	Si-Di	-		-	-
1S945[Japan]	Si-Di	=1S941[Japan]:1000V	-		-
1S946	Si-Di	GI,Uni,200V,0,6A	31a	Shi	BY126..127,BY133..134,1N4003..07,+
1S947	Si-Di	=1S947:400V	31a	-	BY126..127,BY133..134,1N4004..07,+
1S948	Si-Di	=1S947:600V	31a	-	BY126..127,BY133..134,1N4005..07,+
1S949	Si-Di	=1S947:800V	31a	-	BY127,BY133,BY227,1N4006..07,+
1S95	Si-Di	=1S90:600V	34a$	-	BY126..127,BY133..134,1N4005..07,+
1S950	Si-Di	=1S947:1000V	31a	-	BY127,BY133,BY227,1N4007,+
1S951	Si-Di	SS,35V,0,1A,<3ns	31a	Nec	BA318,BAY38,1N4148..49,1N4151,+
1S952	Si-Di	SS,35V,0,15A,<3ns	31a	Nec	BA318,BAY38,1N4148..49,1N4151,+
1S953	Si-Di	SS,35V,0,1A,<3ns	31a	Nec	BA318,BAY38,1N4148..49,1N4151,+
1S954	Si-Di	SS,75V,0,2A,<3ns	31a	Nec	BAW62,BAX95,1N4148..49,1N4151,+
1S955	Si-Di	SS,100V,0,2A,<3ns	31a	Nec	BAW62,BAX95,1N4148..49,1N4151,+
1S956	Si-Di	GI,200V,1,5A	34b&	Hit	BY226..227,BY251..255,1N5393..99,+
1S957	Si-Di	=1S956:400V	34b&	-	BY226..227,BY252..255,1N5395..99,+
1S958	Si-Di	=1S956:600V	34b&	-	BY226..227,BY253..255,1N5397..99,+
1S959	Si-Di	=1S956:800V	34b&	-	BY227,BY254..255,1N5398..99,+
1S96	Si-Di	=1S90:700V	34a$	-	BY127,BY133,BY227,1N4006..07,+
1S960	Si-Di	=1S956:1000V	34b&	-	BY227,BY255,BYX86..87,1N5399,+
1S961	Si-Di	GI,200V,3A	?34	Hit	(BY205/200,BY229/200,BYX49/300,++)
1S962	Si-Di	=1S961:400V	?34	-	(BY205/400,BY229/400,BYX49/600,++)
1S963	Si-Di	=1S961:600V	?34	-	(BY205/600,BY229/600,BYX49/600,++)
1S964	Si-Di	=1S961:800V	?34	-	(BY205/800,BY229/800,BYX49/900,++)
1S965	Si-Di	=1S961:1000V	?34	-	(BY205/1000,BY229/1000,BYX49/1200,++)
1S966	Si-Di	GI-L,200V,20A	32	-	1N4525..30
1S967	Si-Di	=1S966:400V	32	-	1N4526..30
1S968	Si-Di	=1S966:600V	32	-	1N4527..30
1S969	Si-Di	=1S966:800V	32	-	1N4528..30
1S97	Si-Di	=1S90:800V	34a$	-	BY127,BY133,BY227,1N4006..07,+
1S970	Si-Di	=1S966:1000V	32	-	1N4529..30
1S971	Si-Di	GI-L,500V,280A	73b&	Hit	-
1S972	Si-Di	=1S971:600V	73b&	-	-
1S973	Si-Di	=1S971:800V	73b&	-	-

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1S974	Si-Di	=1S971:1000V	73b&	-	-
1S975	Si-Di	=1S971:1300V	73b&	-	-
1S976	Si-Di	=1S971:1500V	73b&	-	-
1S977	Si-Di	SS,35V,0,06A,<2,5ns	34	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S978	Si-Di	=1S977:50V	34	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S98	Si-Di	=1S90:900V	34a$	-	BY127,BY133,BY227,1N4007,+
1S981	Si-Di	SS,30V,0,045A,<2,5ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S982	Si-Di	SS,30V,0,05A,<2,5ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S983	Si-Di	SS,30V,0,06A,<2,5ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S984	Si-Di	SS,50V,0,05A,<2ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S985	Si-Di	SS,50V,0,06A,<2ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S986	Si-Di	SS,50V,0,06A,<2ns	31a	Oki	BA318,BAY38,1N4148..49,1N4151,+
1S987	Si-Di	SS,100V,0,06A,<2ns	31a	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S988	Si-Di	SS,100V,0,06A,<2ns	31a	Oki	BAW62,BAX95,1N4148..49,1N4151,+
1S989	Z-Di	17..21V,3W	32a$	Tos	BZX98/C18,BZY93/C18,ZL18,1N2982
1S99	Si-Di	=1S90:1000V	34a$	-	BY127,BY133,BY227,1N4007,+
1S990(A)	Si-St	0,6..0,8V,0,25W	31a	Njr	BA220,BZ102/0V7,BZX55/C0V8,ZPD1
1S991(A)	Si-St	=1S990:1,3..1,5V	31a	-	BZ102/1V4,BZX75/C1V4,ZTE1,5
1S992	Si-St	=1S990:1,4..2,6V	31a	-	BZ102/2V1,BZX75/C2V1,ZTE2
1S993	Si-St	=1S990:2,4..3,6V	31a	-	-
1S994	Si-St	=1S990:3,4..4,6V	31a	-	-
1S995	Si-Di	35V	31a	Njr	-
1S996(A,B)	Si-Di	5..10V,0,1..0,15A	31a	Njr	-
1S997	Si-Di	10V,0,1A	31a	Njr	-
1S998(A,B)	Si-Di	5..10V,0,1..0,15A	31a	Njr	-
1S999	Si-St	0,55..0,75V,0,05W	31a	Njr	BA220,BZ102/0V7,BZX55/C0V8,ZPD1,+
1SMA10CA..78CA(T3)	Z-Di	=1SMA5.0A..78A:bidirektional	71a(5x2,5)	Ons	-
1SMA5.0A..78A(T3)	Z-Di	SMD,TAZ,5..78V,5%,400W(1ms)	71a(5x2,5)	Ons	BZG03-..,BZG04-..
1SMA5913B..5945B	Z-Di	SMD,3,3..68V,5%,0,5W	71a(5x2,5)	Ons	HZF2..36,RD..FM,MA1Z..,PTZ..
1SMB10CA..78CA(T3)	Z-Di	=1SMB5.0A..170A:bidirektional	71a(5x3,5)	Ons	-
1SMB5.0A..170A(T3)	Z-Di	SMD,TAZ,5..170V,5%,600W(1ms)	71a(5x3,5)	Ons	-
1SMB5913B..5956B	Z-Di	SMD,3,3..200V,5%,0,55W	71a(5x3,5)	Ons	-
1SMC5.0A..78A(T3)	Z-Di	SMD,TAZ,5..78V,5%,1500W(1ms)	71a(7,9mm)	Ons	-
1SMZG06GP	Si-Br	SMD,Gl-Br,600V,0,8A	?4-DIP	Fag	-
1SP	Si-N	=2SC3130-P(Typ-Code/Stempel/marking)	35	Mat	→2SC3130
1SP	Si-N	=2SC3935-P(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC3935
1SQ	Si-N	=2SC3130-Q(Typ-Code/Stempel/marking)	35	Mat	→2SC3130
1SQ	Si-N	=2SC3935-Q(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC3935
1SR	Si-N	=2SC3130-R(Typ-Code/Stempel/marking)	35	Mat	→2SC3130
1SR	Si-N	=2SC3935-R(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC3935
1SR124-..A	Si-Di	Gl/S,100..400V,1A,<400ns	31a	Rhm	BYV12..16,RGP10B..M,RGP15B..M,+
1SR124-100A	Si-Di	Gl/S,100V,1A,<400ns	31a	Rhm	BYT52B..M,BYV12..16,RGP10B..M,+
1SR139-..	Si-Di	Gl,100..600V,1A	31a	Rhm	BY126..127,BY133..135,1N4002..07,+
1SR153-..	Si-Di	Gl/S,100..400V,0,8A,<400ns	31a	Rhm	BYT52B..M,BYV12..16,RGP10B..M,+
1SR154-..	Si-Di	=1S35-..:SMD	71a(5x2,5)	Rhm	-
1SR156-..	Si-Di	=1S153-..:SMD	71a(5x2,5)	Rhm	-
1SR159-200	Si-Di	S,200V,1A,<50ns	71a(5x2,5)	Rhm	-
1SR35-..(A)	Si-Di	Gl,100..400V,1A	31a	Rhm	BY126..127,BY133..135,1N4002..07,+
1SS100	Si-Di	UHF/SHF-Mixer,3GHz	-	Tos	-
1SS101	Si-Di	Schottky-Di,70V,15mA	31a	Nec	BAR28,HSS102,1N5711,1SS285
1SS102	Si-Di	SS,125V,0,15A,<3ns	31a	Nec	1SS116,(BA203)
1SS103	C-Di	VHF-Band-S,35V,<2pF(0V),<0,6e	71a(4mm)	Nec	BA182,BA243,BA283,BA483..484,+
1SS104	Si-Di	Uni,35V,0,1A,Uf<1,3V(0,1A)	31a	Tos	BA127,BA147/50,BA187..190,BA215+
1SS106	Si-Di	Schottky-Di,Dem,SS,11V,0,03A	31a	Hit	BAR10,BAT19,1N5712,1SS281
1SS107	Si-Di	Schottky-Di,22V,15mA,Uf<1V(3mA)	31a	Hit	BAR10,1N5712
1SS108	Si-Di	Schottky-Di,35V,15mA,Uf<1V(3mA)	31a	Hit	HSS100..102,MA776,1S1992
1SS109	Si-Di	Uni,90V,0,15A,Uf<0,8V(10mA)	31a	Hit	BA147/100,BA189..190,BAY19..21,+
1SS11	GaAs-Di	UHF-M,4V,50mA,<0,4pF,9375MHz	-	Nec	-
1SS110	C-Di	VHF/UHF-Band-S,35V,<1,2pF(6V),<0,9e	31a	Hit	BA182,BA243,BA283,BA483..484,+
1SS111	Si-Di	SS,20V,0,15A,<2ns	31a	Hit	BAX80,BAY95,1N4148..49,1N4446..48+
1SS112	Si-Di	=1SS111:40V	31a	-	BAX80,BAY95,1N4148..49,1N4446..48+
1SS113	Si-Di	=1SS111:60V	31a	-	BAW62,BAX95,1N4148..49,1N4446..48+
1SS114	Si-Di	=1SS111:80V	31a	-	BAW62,BAX95,1N4148..49,1N4446..48+
1SS115	Si-Di	=1SS111:100V	31a	-	BAW62,BAX95,1N4148..49,1N4446..48+

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1SS116	Si-Di	=1SS111:120V	31a	-	-
1SS117	Si-Di	SS,35V,0,1A,<3ns	31a	Hit	BA318,BAY38,1N4148..49,1N4446..49+
1SS118	Si-Di	SS,75V,0,2A,<3ns	31a	Hit	BAW62,BAX95,1N4148..49,1N4446..49+
1SS119	Si-Di	Dem,SS,35V,0,15A,<3,5ns	31a	Hit	BA318,BAY38,1N4148..49,1N4446..49+
1SS12	GaAs-Di	UHF-M,10V,50mA,<0,7pF,3060MHz	-	Nec	-
1SS120	Si-Di	=1SS119:70V	31a	Hit	BAW62,BAX95,1N4148..49,1N4446..49+
1SS121	Si-Di	S,75V,0,2A,<50ns	31a	Hit	BAV19..21,BAW49,BAY43,BAY72,+
1SS122	Si-Di	-	31a	Hitachi	BA157..159,BA199/450,BAY89..91,+
1SS122(H)	Si-Di	H:hi-relVersion	-		-
1SS122(H)	Si-Di	Uni,S,400V,0,15A,<10?s	31a	Hit	BA157..159,BA199/450,BAY89..91,+
1SS122H	Si-Di	-	-	-	-
1SS123	Si-Di	SMD,Dual,SS,70V,0,1A,<9ns	35o	Nec	BAV99,HSM123,MA157A
1SS124	Si-Di	Schottky-Di,UHF-Dem,3V,30mA,24GHz	Koax	Nec	-
1SS125	Si-Di	Schottky-Di,UHF-Dem,22V,50mA,10GHz	Koax	Nec	-
1SS13	GaAs-Di	UHF-M,4V,30mA,<0,35pF,9375MHz	-	Nec	-
1SS130	Si-Di	SS,100V,0,13A,<4ns	31a	Rhm	1N4148..49,1N4446..49,1SS115..116
1SS131	Si-Di	SS,90V,0,13A,<4ns	31a	Rhm	1N4148..49,1N4446..49,1SS115..116
1SS132	Si-Di	SS,55V,0,12A,<4ns	31a	Rhm	BAW62,BAX95,1N4148..49,1N4446..49+
1SS133	Si-Di	SS,40V,0,11A,<4ns	31a	Rhm	BA318,BAY38,1N4148..49,1N4446..49+
1SS134	Si-Di	SS,40V,0,05A,<3ns	31a	Rhm	BA318,BAY38,1N4148..49,1N4446..49+
1SS135	C-Di	VHF-Band-S,35V,<1,3pF(6V),<0,6e	31a	Rhm	BA182,BA243,BA283,BA483..484,+
1SS136	Si-Di	SS,75V,0,2A,<2ns	31a	Rhm	BAW62,BAX95,1N4148..49,1N4446..49+
1SS137	Si-Di	=1SS136:55V	31a	Rhm	BAW62,BAX95,1N4148..49,1N4446..49+
1SS138	Si-Di	=1SS136:40V	31a	Rhm	BA318,BAY38,1N4148..49,1N4446..49+
1SS139	Si-Di	S,90V,0,13A,<50ns	31a	Rhm	BAV19..21,BAW49,BAY43,BAY72,+
1SS14	GaAs-Di	UHF-M,3V,25mA,<0,35pF,10GHz	-	Nec	-
1SS140	Si-Di	S,55V,0,12A,<50ns	31a	Rhm	BAV18..21,BAW49,BAY42,BAY72,+
1SS141	Si-Di	S,40V,0,11A,<50ns	31a	Rhm	BAV18..21,BAW49,BAY41,BAY72,+
1SS142	Si-Di	S,Uni,300V,0,2A,<400ns	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS143	Si-Di	=1SS142:250V	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS144	Si-Di	=1SS142:200V	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS145	Si-Di	=1SS142	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS146	Si-Di	=1SS143	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS147	Si-Di	=1SS144	31a	Rhm	BA157..159,BY204/4,BY206..207,+
1SS148	Si-Di	SS,35V,0,1A,<4ns	31a	Tos	BA318,BAY38,1N4148..49,1N4446..49+
1SS149	Si-Di	Uni,250V,0,15A,<5?s	31a	Hit	BA157..159,BY204/4,BY206..207,+
1SS15	GaAs-Di	UHF-M,3V,10mA,<0,22pF,21GHz	-	Nec	-
1SS150	C-Di	VHF-Band-S,32V,<1,2pF(15V),<0,7e	31a	Hit	BA182,BA243,BS283,BA483..484,+
1SS151	Si-Di	Schottky-Di,Dem,S,4V,30mA	31a	Hit	BA480..481,BAR19,BAT29
1SS152	C-Di	VHF-Band-S,35V,<1,7pF(6V),<1e	31a	Hit	BA182,BA243,BS283,BA483..484,+
1SS153	C-Di	SMD,VHF-Band-S,35V,<1,3pF(15V),<0,6e	35e	Nec	BAT18,MA57
1SS154	Si-Di	SMD,Schottky,UHF-M,6V,0,03A,0,8pF	35c	Tos	MA704A
1SS155	C-Di	(Band-S),32V,0,1A,<1,4pF(10V)	31a	Tos	-
1SS157	Ge-Di	Dem,40V,50mA,<0,9pF(1V),40MHz	31a	Say	AA113,AA119,1N34,1N54,1N60
1SS158	Ge-Di	=1SS157:50V	31a	Say	AA113,1N34,1N54,1N60
1SS16	Si-Di	UHF-M,5V,30mA,<0,9pF,855MHz	31a	Nec	-
1SS161	C-Di	VHF-Band-S,30V,<1,6pF(15V),<0,8e	31a	Njr	BA182,BA243,BA283,BA483..483,+
1SS162	C-Di	UHF-Band-S,30V,<1,3pF(15V),<0,7e	31a	Njr	BA244,BA282,BA282,BA482
1SS163	Si-Di	SS,35V,0,15A,<3pF,<4ns	31a	Hit	BA318,BAY38,1N4148..49,1N4446..49+
1SS164	Si-Di	=1SS163:70V	31a	Hit	BAW62,BAX95,1N4148..49,1N4446..49+
1SS165	Si-Di	Schottky,CATV-M,12V,15mA,<1pF(0V)	31a	Hit	BAR10..11,1N5712
1SS166	Si-Di	=1SS165:<1,2pF(0V)	31a	Hit	BAR10..11,1N5712
1SS166A	Si-Di	=1SS165:<0,8pF(0V)	31a	-	BAR10..11,1N5712
1SS168	C-Di	VHF-Tuner,Band-S,35V,<1,2pF(6V)	31a	Hit	BA182,BA243,BA283,BA483..483,+
1SS172	Si-Di	S,120V,0,7A,<20pF,<20ns	31a	Hit	-
1SS173	Si-Di	S,35V,0,1A,<3pF,<12ns	31a	Hit	BA318,BAY17,1N4148..49,1SS113,+
1SS174	Si-Di	Schottky-Di,TV-UHF-M,3V,30mA,<1,2pF	31a	Hit	BA480..481,BAR19,BAT29
1SS175	Si-Di	S,75V,0,15A,<5pF,<100ns	31a	Hit	BA201,BAV19..21,1N4148..4149,+
1SS175A	Si-Di	=1SS175:100V	31a	-	BA202,BAV19..21,1N4148..4149,+
1SS176	Si-Di	SS,35V,0,1A,<1,3pF,<4ns	31a	Tos	BA318,BAY38,BAY71,1N4148..49,+
1SS177	Si-Di	=1SS176:55V	31a	-	BA318,BAX80,BAY38,1N4148..49,+
1SS178	Si-Di	=1SS176:90V	31a	-	BA219,1SS115,1N4148..49,1N4446..49+
1SS181	Si-Di	SMD,Dual,SS,85V,0,1A,<4ns	35m	Tos	BAW56,MA152WA,KDS181,1S2836
1SS184	Si-Di	=1SS181:	35l	-	BAV70,KDS184,MA152WK,1S2838

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1SS187	Si-Di	SMD,SS,85V,0,1A,<4pF,<4ns	35f	Tos	-
1SS190	Si-Di	=1SS187:	35d	Tos	-
1SS193	Si-Di	=1SS187:	35e	Tos	-
1SS196	Si-Di	=1SS187:	35c	Tos	-
1SS197	C-Di	VHF-Tuner,Band-S,35V,<1,7pF(6V)	31a	Hit	BA182,BA243,BA283,BA483..483,+
1SS198	Si-Di	Schottky-Di,Dem,S,10V,30mA,<1,5pF	31a	Hit	BAR10..11,1N5712,1SS106
1SS199	Si-Di	Schottky-Di,Dem,S,30V,15mA,<3pF	31a	Hit	BAT81,HSS101,1S1992,1SS108
1SS200	Si-Di	=1SS181:	41q	Tos	-
1SS201	Si-Di	=1SS184:	41p	Tos	-
1SS202	Si-Di	SS,35V,0,1A,<4pF,<3ns	31a	Nec	BAW62,BAX95,1N4148..49,1N4446..49+
1SS202(1)	Si-Di	=1SS202:100V	31a	-	1N4148..49,1N4446..49,1SS115..116
1SS202-1	Si-Di	-	31a	-	1N4148..49,1N4446..49,1SS115..116
1SS205	Si-Di	S,35V,0,1A,3pF,<100ns	31a	Nec	-BAX90,BAX94,BAY41..43,1N4148..49+
1SS206	Si-Di	=1SS205:75V	31a	Nec	BAW49,BAY43,BAY72,1N4148..49,+
1SS207	Si-Di	=1SS205:100V	31a	Nec	BAW49,BAX12,BAY72,1N4148..49,+
1SS220	Si-Di	SMD,SS,70V,0,1A,<3ns	35e	Nec	-
1SS221	Si-Di	=1SS220:100V	35e	Nec	-
1SS222	Si-Di	=1SS220:	35f	Nec	-
1SS223	Si-Di	=1SS220:100V	35f	Nec	-
1SS226	Si-Di	=1SS184:	35o	Tos	BAV99,HSM123,MA157A
1SS228	Si-Di	Schottky-Di,TV-UHF-M,3V,30mA,<1,1pF	31a	Hit	BA480..481,BAR19,BAT29
1SS23	Si-Di	Schottky-Di,12V,0,1A,Uf<1V(50mA)	-	Nec	BAT47
1SS233	Si-Di	Dual,35V,0,1A,<4pF,<3ns	40p	Nec	MC921
1SS234	Si-Di	=1SS233:75V	40p	Nec	MC921
1SS235	Si-Di	=1SS233:	40q	Nec	MC911
1SS236	Si-Di	=1SS233:75V	40q	Nec	MC911
1SS237(1)	Si-Di	Schottky,UHF-M,10V,35mA,<1pF(0V)	31a	Nec	BAT19,BAT45,1SS88,1SS106
1SS237(-1)	Si-Di	-	31a	NEC	BAT19,BAT45,1SS88,1SS106
1SS238	C-Di	VHF-Tuner,Band-S,20V,<1,2pF,<0,9e	31a	Tos	BA182,BA243,BA283,BA483..483,+
1SS239	Si-Di	Schottky-Di,VHF/UHF,6V,30mA	71a(2,7mm)	Tos	-
1SS24	Ge-Di	Dem,40V,50mA,<0,4pF(1V),40MHz	31a	Unz	AA113,1N34,1N54,1N60
1SS241	C-Di	VHF-Band-S,30V,<1,2pF(6V),<0,9e	71a(2,7mm)	Tos	BA582
1SS242	C-Di	Schottky-Di,VHF-M/Band-S,5V,30mA	71a(2,7mm)	Tos	HSR276
1SS244	Si-Di	S,250V,0,2A,<3pF,<75ns	31a	Rhm	BA198,BAV21,1SS83
1SS245	Si-Di	=1SS244	31a	Rhm	BA198,BAV21,1SS83
1SS247	Si-Di	S,250V,0,2A,1pF,<6ns	31a	Tos	-
1SS248	Si-Di	=1SS247:300V	31a	Tos	-
1SS25	Ge-Di	Dem,40V,50mA,<1pF(1V),40MHz	31a	Unz	AA113,1N34,1N54,1N60
1SS250	Si-Di	SMD,250V,0,1A,<60ns	35e	Tos	BAS21
1SS252	Si-Di	=1SS131	31a	Rhm	→1SS131
1SS253	Si-Di	=1SS132	31a	Rhm	→1SS132
1SS254	Si-Di	=1SS133	31a	Rhm	→1SS133
1SS26	Ge-Di	Dem,40V,50mA,<1pF(1V),40MHz	31a	Unz	AA113,1N34,1N54,1N60
1SS265	Si-Di	=1SS135	31a	Rhm	→1SS135
1SS268	Si-Di	SMD,Dual,VHF-Band-S,30V,<1,2pF,<0,9e	35l	Tos	HSM2693
1SS269	Si-Di	=1SS268:	35m	-	HSM2694
1SS27	Ge-Di	Dem,40V,50mA,<1pF(1V),40MHz	31a	Unz	AA113,1N34,1N54,1N60
1SS270	Si-Di	Dem,SS,30V,0,15A,<3pF,<3,5ns	31a	Hit	BA221,BAY74,1N4148..49,1N4154,+
1SS270A	Si-Di	=1SS270:70V	31a	-	BAW62,BAX95,1N4148..49,1N4151,+
1SS271	Si-Di	SMD,Schottky,Dual,VHF/UHF,6V,30mA	35o	Tos	BAT68-04
1SS271	Si-Di	Uf<0,55V(10mA),<1pF(0V)	-		-
1SS272	Si-Di	SMD,Dual,SS,85V,0,1A,<2pF,<4ns	44s2	Tos	-
1SS276	Si-Di	Schottky-Di,Tuner-M,3V,30mA,<0,8pF	31a	Hit	BA480..481,BAR19,BAT29
1SS277	C-Di	VHF/UHF-Band-S,35V,<1,2pF,<0,5e	31a	Hit	BA282,BA284,BA482
1SS279	C-Di	VHF/UHF-Band-S,35V,<1pF(15V),<1e	31a	Nec	BA244,BA282,BA284,BA482
1SS28	Ge-Di	Dem,30V,50mA,<1pF(1V)	31a	Unz	AA113,1N34,1N54,1N60
1SS280	C-Di	VHF/UHF-Band-S,35V,<2pF(15V),<0,6e	31a	Nec	BA244,BA282,BA284,BA482
1SS281	Si-Di	Schottky,UHF-M,10V,35mA,<1pF(0V)	31a	Nec	BAT19,BAT45,1SS88,1SS106
1SS282	Si-Di	Schottky,UHF-M,5V,50mA,<1pF(0V)	31a	Nec	1S1925
1SS283	Si-Di	Schottky,UHF-M,5V,30mA,<0,9pF(0V)	31a	Nec	BAR10,BAT45,1N5712
1SS285	Si-Di	Schottky,UHF-M,70V,15mA,<2pF(0V)	31a	Nec	HSS102
1SS286	Si-Di	Schottky-Di,Dem,S,25V,35mA,<1,2pF	31a	Hit	BAT81,HSS101,1S1992,1SS108
1SS287	Si	S	-	Tos	-
1SS288	Si	S	-	Tos	-

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1SS289	Si	S	-	Tos	-
1SS29	Ge-Di	Dem,40V,50mA,<0,6pF(1V),40MHz	31a	Unz	AA113,1N34,1N54,1N60
1SS290	Si-Di	=1SS139	31a	Rhm	→1SS139
1SS291	Si-Di	=1SS140	31a	Rhm	→1SS140
1SS292	Si-Di	=1SS141	31a	Rhm	→1SS141
1SS293	Si-Di	Schottky-Di,S,45V,0,1A,Uf<0,6V	41f	Tos	BAT86
1SS294	Si-Di	=1SS293:SMD	35e	-	1SS348
1SS295	Si-Di	SMD,Schottky,Dual,UHF-M,4V,0,05A	35o	Tos	MA730,1SS366
1SS30	Ge-Di	Dem,75V,50mA,<1pF(1V),455kHz	31a	Unz	-
1SS300	Si-Di	=1SS181:	35m(2mm)	Tos	-
1SS301	Si-Di	=1SS184:	35l(2mm)	Tos	-
1SS302	Si-Di	=1SS226:	35o(2mm)	Tos	-
1SS306	Si-Di	SMD,Dual,S,250V,0,1A,<3pF,<60ns	44s2	Tos	-
1SS307	Si-Di	SMD,35V,0,1A,Uf<1,3V(0,1A),<6pF	35e	Tos	BAS19..21,BAS29
1SS308	Si-Di	SMD,Quad,SS,85V,0,1A,<2pF,<4ns	45bb	Tos	-
1SS309	Si-Di	SMD,Quad,SS,85V,0,1A,<2pF,<4ns	45bc	Tos	-
1SS31	Ge-Di	Dem,50V,50mA,<1pF(1V)	31a	Unz	AA113,1N34,1N54,1N60
1SS311	Si-Di	SMD,S,420V,0,1A,1,5?s	35e	Tos	HSM122
1SS312	C-Di	=1SS268:	35l(2mm)	Tos	-
1SS313	C-Di	=1SS269:	35m(2mm)	Tos	-
1SS314	C-Di	=1SS241:	71a(1,7mm)	Tos	BA592,MA77,1SS356
1SS315	C-Di	=1SS242:	71a(1,7mm)	Tos	HSU276
1SS317	C-Di	VHF/UHF-Band-S,35V,<1,5pF,<0,6e	31a	Nec	BA244,BA282,BA284,BA482
1SS318	C-Di	SMD,VHF-Band-S,<1,2pF(6V),<0,9e	71a(1,7mm)	Rhm	BA592,1SS314
1SS319	Si-Di	=1SS293:SMD,Dual	44s2	Tos	-
1SS321	Si-Di	SMD,Schottky-Di,Dual,S,12V,0,05A	35l	Tos	-
1SS322	Si-Di	=1SS294:SMD	35e(2mm)	Tos	-
1SS332	Si-Di	SMD,SS,40V,0,1A,<3pF,<4ns	71a(1,7mm)	Rhm	MA110,1SS354,1SS355
1SS336	Si-Di	SMD,Dual,S,85V,0,2A,7pF,<20ns	35m	Tos	-
1SS337	Si-Di	=1SS336:	35l	Tos	-
1SS344	Si-Di	SMD,Schottky-Di,S,25V,0,5A,20ns	35e	Tos	1SS349
1SS345	Si-Di	SMD,Schottky,UHF-M,5V,10mA,0,45pF	35e	Say	-
1SS348	Si-Di	SMD,Schottky-Di,S,85V,0,1A	35e	Tos	-
1SS349	Si-Di	SMD,Schottky-Di,S,25V,1A,Uf<0,55V	35e	Tos	-
1SS350	Si-Di	SMD,Schottky-Di,UHF-M,5V,30mA	35e	Say	BAT17
1SS351	Si-Di	=1SS350:Dual	35o	Say	-
1SS352	Si-Di	SMD,SS,85V,0,1A,<3pF,<4ns	71a(1,7mm)	Tos	HSU119,MA111,1SS353
1SS353	Si-Di	SMD,SS,90V,0,1A,<3pF,<4ns	71a(1,7mm)	Rhm	HSU119,MA111,1SS352
1SS354	Si-Di	SMD,SS,50V,0,1A,<3pF,<4ns	71a(1,7mm)	Rhm	HSU119,MA111,1SS352,1SS353
1SS355	Si-Di	SMD,SS,40V,0,1A,<3pF,<4ns	71a(1,7mm)	Rhm	HSU119,MA111,1SS332,1SS352,1SS354
1SS356	C-Di	HF-Band-S,30V,0,1A,<1,2pF,<0,9e	71a(1,7mm)	Rhm	BA592,MA77,1SS314
1SS357	Si-Di	=1SS293:SMD	71a(1,7mm)	Tos	KDR357
1SS358	Si-Di	=1SS345:Dual	35o	Say	-
1SS360	Si-Di	-	35(1,6mm)	Toshiba	1SS360
1SS360(F)	Si-Di	=1SS181:	35m(1,6mm)	Tos	-
1SS360F	Si-Di	-	35(1,6mm)	Toshiba	1SS360F
1SS361	Si-Di	-	35(1,6mm)	Toshiba	1SS361
TSS361(F)	Si-Di	=1SS184:	35l(1,6mm)	Tos	-
1SS361F	Si-Di	-	35(1,6mm)	Toshiba	1SS361F
1SS362	Si-Di	=1SS184:	35o(1,6mm)	Tos	-
1SS364	Si-Di	=1SS268:	35l(1,6mm)	Tos	-
1SS365	Si-Di	SMD,Schottky-Di,10V,35mA,0,85pF	35e	Say	MA704
1SS366	Si-Di	=1SS365:Dual	35q	Say	MA730,1SS295
1SS367	Si-Di	SMD,Schottky-Di,S,15V,0,1A	71a(1,7mm)	Tos	KDR367
1SS368	Si-Di	=1SS352:	71a(1,3mm)	Tos	1SS387,1SS400
1SS369	Si-Di	=1SS357:	71a(1,3mm)	Tos	1SS388
1SS370	Si-Di	=1SS250:	35e(2mm)	Tos	-
1SS371	C-Di	=1SS241:	71a(1,3mm)	Tos	-
1SS372	Si-Di	=1SS367:Dual	35o(2mm)	Tos	-
1SS373	Si-Di	=1SS367:	71a(1,3mm)	Tos	KDR367E,1SS389
1SS374	Si-Di	=1SS367:Dual	35o(3mm)	Tos	-
1SS375	Si-Di	=1SS365:Dual	35o(2mm)	Say	-
1SS376	Si-Di	SMD,300V,0,1A,<100ns	71a(1,7mm)	Rhm	HSU83
1SS377	Si-Di	=1SS367:Dual	35l(3mm)	Tos	-

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1SS378	Si-Di	=1SS367:Dual	3SI(2mm)	Tos	KDR378
1SS379	Si-Di	=1SS367:Dual	3So(3mm)	Tos	-
1SS380	Si-Di	SMD,Uni,40V,0,1A,Ir=10nA(20V)	71a(1,7mm)	Rhm	-
1SS382	Si-Di	SMD,Dual,SS,85V,0,1A,<4ns	44s2(2mm)	Tos	-
1SS383	Si-Di	SMD,Schottky,Dual,45V,0,1A	44s2(2mm)	Tos	-
1SS384	Si-Di	SMD,Schottky,Dual,15V,0,1A	44s2(2mm)	Tos	-
1SS385	Si-Di	-	35(1,6mm)	Toshiba	1SS385
1SS385(F)	Si-Di	SMD,Schottky,Dual,15V,0,1A	3SI(1,6mm)	Tos	-
1SS385F	Si-Di	-	35(1,6mm)	Toshiba	1SS385F
1SS387	Si-Di	SMD,SS,85V,0,1A,<4ns	71a(1,3mm)	Tos	1SS368,1SS400
1SS388	Si-Di	SMD,Schottky,45V,0,1A	71a(1,3mm)	Tos	1SS369
1SS389	Si-Di	SMD,Schottky,15V,0,1A	71a(1,3mm)	Tos	1SS373
1SS390	C-Di	SMD,VHF-Band-S,35V,<1,2pF,<0,9e	71a(1,3mm)	Rhm	(=1SS318)
1SS391	Si-Di	SMD,Schottky,Dual,15V,0,1A	44s2	Tos	-
1SS392	Si-Di	SMD,Schottky,Dual,45V,0,1A	3SI	Tos	BAS40-05
1SS393	Si-Di	=1SS392:	3SI(2mm)	Tos	BAS40-05W
1SS394	Si-Di	SMD,Schottky,15V,0,1A	35e	Tos	BAS125,RB420D,RB421D
1SS395	Si-Di	=1SS394:	35e(2mm)	Tos	-
1SS396	Si-Di	=1SS392:	35o	Tos	BAS40-04
1SS397	Si-Di	SMD,420V,0,1A,500ns	35e(2mm)	Tos	-
1SS398	Si-Di	SMD,Dual,420V,0,1A,500ns	35o	Tos	-
1SS399	Si-Di	=1SS398:	44s2	Tos	-
1SS400	Si-Di	SMD,SS,90V,0,1A,<4ns	71a(1,3mm)	Rhm	1SS368,1SS387
1SS401	Si-Di	SMD,Schottky-Di,S,25V,0,3A	35e(2mm)	Tos	-
1SS402	Si-Di	SMD,Schottky,Dual,25V,0,05A	44s2(2mm)	Tos	-
1SS403	Si-Di	SMD,S,250V,0,1A,<3pF,<60ns	71a(1,7mm)	Tos	BAS21H,BAS321
1SS404	Si-Di	SMD,Schottky-Di,S,25V,0,3A	71a(1,7mm)	Tos	BAT165
1SS41	Si-Di	SS,100V,0,13A,<4ns	31a	Rhm	BA219,1N4148..49,1N4446..49
1SS42	Si-Di	Schottky-Di,UHF-M,5V,30mA,900MHz	31a	Tos	BA480..481,BAR19,BAT29
1SS43	Si-Di	Schottky-Di,Modulator,5V,30mA	31a	Nec	BA480..481,BAR19,BAT29
1SS48	Si-Di	Dual,70V,0,1A	S	Fui	-
1SS49	Si-Di	SS,35V,0,1A,<10ns	31a	Mat	BAY69,BAY71,1N4148..49,1N4446..49+
1SS50	Si-Di	SS,50V,0,1A,<4ns	31a	Mat	BA318,BAY38,1N4148..49,1N4446..49+
1SS51	Si-Di	SS,75V,0,1A,<4ns	31a	Mat	BAW62,BAX95,1N4148..49,1N4446..49+
1SS52	Si-Di	SS,35V,0,1A,<3ns	-	Nec	BA318,BAY38,1N4148..49,1N4446..49+
1SS53	Si-Di	S,35V,0,1A,<100ns	31a	Nec	BAX90,BAX94,BAY41..43,1N4148..49+
1SS54	Si-Di	=1SS53:75V	31a	Nec	BAW49,BAY43,BAY72,1N4148..49,+
1SS55	Si-Di	=1SS53:100V	31a	Nec	BAW49,BAX12,BAY72,1N4148..49,+
1SS68	-Di	SS,40V,45mA,<6ns	31a	Fui	-
1SS69	Si-Di	Schottky-Di,UHF-Dem/M,4V,937SMHz	Koax	Nec	BA480..481,BAR19,BAT29
1SS70	Si-Di	Schottky-Di,UHF-M,4V,30mA,9375MHz	Koax	Nec	BA480..481,BAR19,BAT29
1SS78	Si-Di	Schottky-Di,UHF-Dem/M,5V,855MHz	31a	Nec	BA480..481,BAR19,BAT29
1SS780	Si-Di	-		Rohm	-
1SS81	Si-Di	S,200V,0,2A,<100ns	31a	Hit	BA197..198,BAV20..21,BAW50
1SS82	Si-Di	=1SS81:250V	31a	-	BA198,BAV21
1SS83	Si-Di	=1SS81:300V	31a	-	-
1SS84	Si-Di	S,75V,0,15A,<50ns	31a	Hit	BAV19..21,BAW49,BAY43,BAY72,+
1SS85	C-Di	VHF-Band-S,35V,<1,2pF(6V),<0,9e	31a	Hit	BA182,BA243,BA283,BA483..484,+
1SS86	Si-Di	Schottky-Di,TV,UHF-M,3V,30mA	31a	Hit	-
1SS87	Si-Di	Schottky-Di,TV,UHF-M,3V,15mA	31a	Hit	-
1SS88	Si-Di	Schottky-Di,UHF-M,CATV,10V,15mA	31a	Hit	BAT19,1SS106
1SS90	Si-Di	Schottky-Di,UHF-M,5V,30mA,<0,9pF	31a	Hit	BA480..481,BAR19,BAT29
1SS91	C-Diode	VHF-Band-S,30V,<2pF(15V),<0,6Ω	31a	Njr	BA182,BA243,BA283,BA483..484..
1SS91(-G,-S)	C-Di	-G:<1,1pF(15V),-S:<1,6pF(15V)	-		-
1SS91(-G,-S)	C-Di	VHF-Band-S,30V,<2pF(15V),<0,6e	31a	Njr	BA182,BA243,BA283,BA483..484,+
1SS91-G	C-Diode	VHF-Band-S,30V,<1,1pF(15V),<0,6Ω	31a	Njr	BA182,BA243,BA283,BA483..484,+
1SS91-S	C-Diode	VHF-Band-S,30V,<1,6pF(15V),<0,6Ω	31a	Njr	BA182,BA243,BA283,BA483..484,+
1SS92	Si-Di	SS,75V,0,2A,<2ns	31a	Rhm	BAW62,BAX95,1N4148..49,1N4446..49+
1SS93	Si-Di	=1SS92:55V	31a	Rhm	BAW62,BAX95,1N4148..49,1N4446..49+
1SS94	Si-Di	=1SS92:40V	31a	Rhm	BAW62,BAY95,1N4148..49,1N4446..49+
1SS97	Si-Di	-	31a	NEC	HSS100..102
1SS97(1,2)	Si-Di	-1:Uf<1V(35mA),-2:30mA,Uf<1V(35mA)	-		-
1SS97(1,2)	Si-Di	Schottky-Di,10V,35mA,Uf<0,55V(10mA)	31a	Nec	HSS100..102
1SS97-1	Si-Di	-	31a	NEC	HSS100..102

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1SS97-2	Si-Di	-	31a	NEC	HSS100..102
1SS98	Si-Di	Schottky-Di, 5V, 50mA, Uf<0,45V(10mA)	31a	Nec	1S1925
1SS99	Si-Di	Schottky-Di, 5V, Uf<0,23V(1mA)	31a	Nec	-
1SV100	C-Di	AM-Tuning, 15V, 500pF(1V)	41d	Tos	BB112, BB130, BB509, 1SV134..135, +
1SV101	C-Di	VHF-AFC, FM-Tuner, 15V, 12..14pF(9V)	41d	Tos	BA125, BB119, 1SV114, 1SV125
1SV102	C-Di	HiFi-AM-Tuning, 360..450pF(2V)	41d	Tos	BB112, BB130, BB509, 1SV134..135, +
1SV103	C-Di	Dual, FM-Tuning, 34V, 13,2..16,2pF(30V)	41p	Tos	BB104, BB204, BB304, MV104, 1SV109
1SV104	C-Di	Dual, FM-Tuning, 30V, 37..42pF(3V)	7p	Njr	BB104, BB204, BB304, MV104, 1SV109
1SV109	C-Di	Dual, FM-Tuning, 30V, 8..12pF(25V)	7p	Hit	BB104, BB204, BB304, MV104, 1SV55
1SV110	C-Di	VHF-Tuning, 30V, 2..2,5pF(25V), <1e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV111	C-Di	UHF-Tuning, 30V, 2..2,3pF(25V), <0,82e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV112	C-Di	VHF-Tuning, 30V, 2,5..3pF(25V), <1,2e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV113	C-Di	VHF-Tuning, 30V, 2,4..3pF(25V), <1,2e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV114	C-Di	TV/FM-Tuner-AFC, 15V, 6,8..9pF(6V)	31a	Hit	BB119, 1SV50, 1SV114, 1SV125
1SV115	C-Di	AM-Tuning, 30V, 16..25/300pF(25/1V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV116	C-Di	AM-Tuning, 30V, 16..26/150pF(25/1V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV118	C-Di	AM-Tuning, 30V, 18..30/610pF(25/2V)	7d	Nec	BB112, BB130, BB509, 1SV134..135, +
1SV12	Si-Di	UHF-Multiplier, 45V, 0,4..0,8pF, 10GHz	Koax	Njr	-
1SV121	PIN-Di	HF-Abschw./attenuator, 100V, 0,1A	31a	Hit	-
1SV122	PIN-Di	30V, 0,4pF(30V), 0,8e(100MHz)	Koax	Nec	-
1SV123	C-Di	UHF-Tuning, 35V, 12,5pF(3V), <0,6e	71a(4mm)	Tos	BB105, BB205, BB305, BB405, BB505+
1SV124	C-Di	VHF-Tuning, 32V, 2,5..3,2pF(28V), <1e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV125	C-Di	VHF/UHF-AFC, 30V, 6,8..9pF(6V), <1,2e	31a	Hit	BA125, BB119, 1SV114
1SV126	C-Di	FM/VHF-Tuning, 30V, 4,3..6pF(25V)	31a	Hit	BB109, BB143, BBY30, MV109, 1SV50, +
1SV128	PIN-Di	SMD, VHF/UHF, AGC, 50V, 0,05A, 0,25pF	35e	Tos	MA551, 1SV233
1SV129	C-Di	AM-Tuning, 15V, 450..600pF(1V)	12a	Njr	BB112, BB130, BB509, 1SV134..135, +
1SV13	Si-Di	UHF-Multiplier, 45V, 0,8..1,6pF, 10GHz	Koax	Njr	-
1SV132	C-Di	UHF-Tuning, 30V, 2..2,3pF(25V), <0,6e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV133	C-Di	VHF-Tuning, 30V, >2,4pF(25V), <1e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV134	C-Di	AM-Tuning, 15V, 20..32/400..550pF(8/1V)	31a	Hit	BB112, BB130, BB509, 1SV102, 1SV129+
1SV135	C-Di	AM-Tuning, 28V, 15..25pF(25V)	31a	Hit	BB112, BB130, BB509, 1SV102, 1SV129+
1SV136	C-Di	VHF/UHF-Tuning, 30V, 2,1..2,4pF(25V)	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV138	C-Di	CATV-Tuning, 30V, 2,4..3,2pF(25V)	?71a(4mm)	Tos	MA337, MA338, MA353
1SV14	Si-Di	UHF-Multiplier, 45V, 1,6..3pF, 10GHz	Koax	Njr	-
1SV145	C-Di	VHF/UHF-Tuner/AFC, 34V, 3,3o5,7pF(10V)	31a	Hit	BB119, 1SV114, 1SV125
1SV146	C-Di	VHF/UHF-Tuner/AFC, 34V, 3,3o5,7pF(10V)	31a	Hit	BB119, 1SV114, 1SV125
1SV147	C-Di	Dual, FM-Tuning, 15V, 11,7..13,7pF(8V)	41p	Tos	BB104, BB204, BB304, MV104, 1SV109
1SV148	C-Di	UHF-Tuning, 28V, 2..3pF(25V), <0,6e	71a(4mm)	Rhm	BB105, BB205, BB305, BB405, BB505+
1SV149	C-Di	AM-Tuning, 15V, 485/19,9..30pF(1/8V)	41d	Tos	BB509, MV1401..1404, 1SV134..135, +
1SV15	Si-Di	UHF-Multiplier, 45V, 2..6pF, 10GHz	Koax	Njr	-
1SV151	C-Di	FM/VHF-Tuner-AFC, 20V, 14..26pF(10V)	31a	Hit	BB119, 1SV114, 1SV125, 1SV145..146
1SV153	C-Diode	VHF/UHF-Tuning, 35V, 2,11..2,43pF, <0,6Ω(470MHz)	71a(2,7mm)	Tos	BB515, BB721, BB723, BB729..731
1SV153(A)	C-Di	<0,6e(470MHz), A: <0,55e(470MHz)	-		-
1SV153(A)	C-Di	SMD, VHF/UHF-Tuning, 35V, 2,11..2,43pF	71a(2,7mm)	Tos	BBS15, BB721, BB723, BB729..731
1SV153A	C-Diode	VHF/UHF-Tuning, 35V, 2,11..2,43pF, <0,55Ω(470MHz)	-		-
1SV154	PIN-Di	HF-S, 65V, 0,1A, <0,8pF, <2,5e(100MHz)	31a	Hit	-
1SV155	C-Di	VHF-Tuning, 30V, 5..7pF(25V)	31a	Hit	BB205, BB305, BB405, BB505, 1SV124+
1SV156	PIN-Di	HF-Abschw./Atten., 30V, 0,05A, <0,6pF	31a	Nec	-
1SV157	PIN-Di	HF-Abschw./Atten., 50V, 0,05A, <0,9pF	31a	Nec	1SV196
1SV16	Si-Di	UHF-Multiplier, 60V, 0,3..0,6pF, 10GHz	Koax	Njr	-
1SV160	C-Di	SMD, FM-AFC, 15V, 7..14pF(4V), <1,2e	35c	Tos	-
1SV161	C-Di	SMD, CATV-Tuning, 35V, 2,5..3,2pF(25V)	71a(2,7mm)	Tos	BB721, BB723, BB729..731
1SV163	C-Di	VHF/UHF-AFC, 30V, 3..6,4pF(10V)	31a	Nec	BB117, BB417
1SV164	C-Di	VHF/UHF-Tuning, 30V, 2..2,3pF(25V)	31a	Nec	BB405, BB505, 1SV111, 1SV148
1SV165	C-Di	VHF/UHF-Tuning, 30V, 2..2,5pF(25V)	31a	Nec	BB405, BB505, 1SV111, 1SV148
1SV166	C-Di	FM/VHF-Tuning, 30V, 4,9..5,8pF(25V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV50
1SV166(1)	C-Di	FM/VHF-Tuning, 30V, 4,9..5,8(25V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV50
1SV166(-1)	C-Diode	FM/VHF-Tuning, 30V, 4,9..5,8(25V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV50
1SV166S	C-Di	VHF-VCO, 30V, 23..36pF(3V)	31a	Nec	-
1SV167	C-Di	VHF/CATV-Tuning, 30V, 2,8..3,3pF(25V)	31a	Nec	1SV209
1SV169	C-Di	VHF/UHF-Tuning, 30V, 2,1..2,5pF(25V)	31a	Nec	BB405, BB505, 1SV111, 1SV148
1SV17	Si-Di	UHF-Multiplier, 60V, 0,8..6pF, 10GHz	Koax	Njr	-
1SV170	C-Di	VHF/UHF-AFC, 30V, 13,7..17pF(2V)	31a	Nec	BB117, BB417
1SV172	C-Di	0,25pF(50V), Rs=7e(10mA, 100MHz)	-		-

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1SV172	C-Di	SMD, Dual, VHF/UHF-Band, AGC, 50V	35o	Tos	-
1SV178	PIN-Di	Antenn.-S, 65V, 0,15A, <0,8pF(6V)	31a	Hit	-
1SV178	PIN-Di	Rs<2,5e(10mA, 100MHz)	-		-
1SV18	Si-Di	UHF-Multiplier, 60V, 1..2pF, 10GHz	Koax	Njr	-
1SV183	C-Di	UHF-Tuning, VC0, 28V, 2..4pF(2V)	31a	Nec	1SV210
1SV184	C-Di	FM/VHF-Tuning, VC0, 15V, 40..50pF(2V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV213
1SV186	C-Di	SMD, UHF/SHF-Tuning, 3,3..4,5pF(2V)	71a(2,7mm)	Tos	-
1SV187	PIN-Di	<2,4pF(0V), Rs<5,2e(10mA, 100MHz)	-		-
1SV187	PIN-Di	Antenn.-S, HF-Abschw., 60V, 0,05A	31a	Hit	MI308, MI407, 1SV178
1SV188	C-Di	SMD, VHF/UHF-Tuning, 30V, 2,1..2,5(25V)	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV19	Si-Di	UHF-Multiplier, 60V, 2..4pF, 10GHz	Koax	Njr	-
1SV191	C-Di	VHF/CATV-Tuning, 30V, 2,5..3pF(25V)	31a	Nec	1SV167, 1SV209
1SV193	C-Di	SMD, VHF/UHF-Tuning, 30V, 2,1o2,4pF(25V)	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV194	C-Di	SMD, VHF-Tuning, 30V, 2,5..3,1pF(25V)	71a(2,7mm)	Hit	BB419, BB619..620
1SV196	PIN-Di	HF-Abschw./Atten., 50V, 0,05A, <0,9pF	31a	Nec	1SV157
1SV196	PIN-Di	Rs<7e/>1ke(10/0,01mA, 100MHz)	-		-
1SV20	Si-Di	UHF-Multiplier, 60V, 4..8pF, 10GHz	Koax	Njr	-
1SV200	C-Di	SMD, VHF-Tuning, 30V, 2,55o3,16pF(25V)	71a(2,7mm)	Hit	BB419, BB619..620
1SV202	C-Di	SMD, UHF-Tuning, 30V, 2,1..2,39pF(25V)	71a(2,7mm)	Hit	BB721, BB723, BB729..731
1SV203	C-Di	SMD, VHF-Tuning, 30V, 2,68o3,12pF(25V)	71a(2,7mm)	Hit	BB419, BB619..620
1SV204	C-Di	SMD, VHF/UHF-AFC, 35V, 3,3..5,7pF(10V)	71a(2,7mm)	Tos	-
1SV205	C-Di	SMD, Tuning, 35V, 2,15..2,39pF(25V)	71a(2,7mm)	Rhm	BB721, BB723, BB729..31, 1SV202
1SV207	C-Di	VHF/UHF, 30V, 30..33pF(2V)	31a	Rhm	-
1SV209	C-Di	VHF/CATV-Tuning, 30V, 2,6..3pF(25V)	31a	Nec	1SV167
1SV21	Si-Di	Varaktor, 45V, <5,2pF(0V)	Koax	Njr	-
1SV210	C-Di	VHF/UHF-Tuning, VC0, 28V, 0,6o0,8pF(20V)	31a	Nec	1SV183
1SV211	C-Di	SMD, UHF-CATV-Tuning, 33..39pF(2V)	71a(2,7mm)	Tos	-
1SV212	C-Di	SMD, UHF-VC0, 5,5..6,5pF(10V)	71a(2,7mm)	Tos	-
1SV213	C-Di	FM/VHF-Tuning, VC0, 15V, 3,5..6pF(10V)	31a	Nec	BB109, BB143, BBY30, MV109, 1SV184
1SV214	C-Di	=1SV153A:	71a(1,7mm)	Tos	BB535, MA360, MA372, 1SV223
1SV215	C-Di	=1SV161:	71a(1,7mm)	Tos	MA366, 1SV232
1SV216	C-Di	=1SV204:	71a(1,7mm)	Tos	-
1SV217	C-Di	=1SV211:	71a(1,7mm)	Tos	MA371
1SV218	C-Di	VHF/CATV-Tuning, 35V, 2,5..3pF(25V)	71a	Nec	-
1SV219	C-Di	VHF/CATV-Tuning, 35V, 2,6..3pF(25V)	71a	Nec	-
1SV22	Si-Di	Varaktor, 45V, <12,2pF(0V)	Koax	Njr	-
1SV220	C-Di	VHF/UHF-Tuning, VC0, 35V, 2..2,5pF(25V)	71a	Nec	BB515, BB721, BB723
1SV221	C-Di	VHF/UHF-Tuning, VC0, 35V, 2,1o2,5pF(25V)	71a	Nec	BB515, BB721, BB723
1SV222	C-Di	VHF/UHF-Tuning, VC0, 35V, 5o6,3pF(10V)	71a	Nec	-
1SV223	C-Di	=1SV205:	71a(1,7mm)	Rhm	BB535, MA360, MA372, 1SV214
1SV224	C-Di	SMD, CATV, 35V, 1,7..2,1pF(20V)	71a(2,7mm)	Tos	-
1SV225	C-Di	SMD, Dual, FM-Tuning, 32, 6,6o7,7pF(30V)	35l	Tos	-
1SV226	C-Di	SMD, CATV-Tuning, 35V, 2,7o3,4pF(25V)	71a(2,7mm)	Tos	-
1SV227	C-Di	SMD, CATV-Tuning, 35V, 2,75o3,1pF(25V)	71a(2,7mm)	Tos	-
1SV228	C-Di	SMD, Dual, FM-Tuning, 15V, 12,7(8V)	35l	Tos	-
1SV229	C-Di	=1SV212:	71a(1,7mm)	Tos	-
1SV23	Si-Di	Varaktor, 90V, <12,2pF	Koax	Njr	-
1SV230	C-Di	=1SV224:	71a(1,7mm)	Tos	-
1SV231	C-Di	=1SV226:	71a(1,7mm)	Tos	BB639, MA365, MA374
1SV232	C-Di	=1SV227:	71a(1,7mm)	Tos	MA366, 1SV215
1SV233	PIN-Di	Rs=5e(10mA, 100MHz)	-		-
1SV233	PIN-Di	SMD, VHF/UHF-AGC, 50V, 0,05A, 0,23pF	35e	Say	MA551, 1SV128
1SV234	PIN-Di	=1SV233: Dual	35o	Say	-
1SV237	PIN-Di	0,25pF(50V), Rs=4e(10mA, 100MHz)	-		-
1SV237	PIN-Di	SMD, Dual, VHF/UHF-Band, AGC, 50V	44s2	Tos	-
1SV238	C-Di	SMD, CATV-Tuning, 35V, 2,75o3,25pF(25V)	71a(1,7mm)	Tos	MA355, MA357, MA366, 1SV269
1SV239	C-Di	SMD, UHF-VC0, 15V, 1,5..2pF(10V)	71a(1,7mm)	Tos	-
1SV24	Si-Di	Varaktor, 90V, <32,2pF	Koax	Njr	-
1SV241	PIN-Di	SMD, VHF/UHF, 50V, 0,23pF, 5e(100MHz)	45	Say	-
1SV242	C-Di	2,43..3pF(28V)	-		-
1SV242	C-Di	SMD, Dual, VHF/UHF-Tuning, 35V	35l	Tos	-
1SV242(SM)	C-Di	=1SV242:	71a(2,7mm)	-	-
1SV245	C-Di	0,61..0,77pF(25V), Rs<2e(470MHz)	-		-
1SV245	C-Di	SMD, UHF/SHF-Tuning, 35V	71a(1,7mm)	Tos	MA368, MA373, HVU12, HVU314, HVU316

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1SV246	PIN-Di	=1SV233:Dual	35o(2mm)	Say	-
1SV247	PIN-Di	=1SV233:	35e(2mm)	Say	-
1SV248	PIN-Di	=1SV250:	35(2mm)	Say	-
1SV249	PIN-Di	=1SV251:	35(2mm)	Say	-
1SV250	PIN-Di	SMD,VHF/UHF,50V,0,23pF,3,5e(100MHz)	35(2,9mm)	Say	-
1SV251	PIN-Di	=1SV250:Dual	35(2,9mm)	Say	-
1SV252	C-Di	=1SV172:	35o(2mm)	Tos	-
1SV254	C-Di	=1SV153A:	71a(1,3mm)	Tos	-
1SV255	C-Di	=1SV161:	71a(1,3mm)	Tos	-
1SV256	C-Di	=1SV204:	71a(1,3mm)	Tos	-
1SV257	C-Di	=1SV212:	71a(1,3mm)	Tos	-
1SV258	C-Di	=1SV224:	71a(1,3mm)	Tos	-
1SV259	C-Di	=1SV227:	71a(1,3mm)	Tos	-
1SV26	PIN-Di	110V,0,05A,0,3pF,1,7GHz	-	Nec	-
1SV260	C-Di	=1SV239:	71a(1,3mm)	Tos	-
1SV261	C-Di	=1SV245:	71a(1,3mm)	Tos	-
1SV262	C-Di	SMD,UHF-CATV-Tuning,36V,2,6o3pF(25V)	71a(1,7mm)	Tos	-
1SV263	PIN-Di	=1SV266:	35(2mm)	Say	-
1SV264	PIN-Di	=1SV267:	35(2mm)	Say	-
1SV265	PIN-Di	SMD,VHF/UHF,50V,0,23pF,2,5e(100MHz)	45	Say	-
1SV266	PIN-Di	SMD,VHF/UHF,50V,0,23pF,2,5e(100MHz)	35(2,9mm)	Say	-
1SV267	PIN-Di	=1SV266:Dual	35(2,9mm)	Say	-
1SV268	PIN-Di	SMD,VHF/UHF,50V,0,7pF,0,5e(470MHz)	39	Say	-
1SV269	C-Di	SMD,CATV-Tuning,36V,2,5o2,9pF(25V)	71a(1,7mm)	Tos	HVU306A,MA355,MA357,MA366,1SV238
1SV27	PIN-Di	110V,0,05A,0,3pF,1,7GHz	Koax	Nec	-
1SV270	C-Di	SMD,UHFVCO,7,3..8,7pF(4V)	71a(1,7mm)	Tos	HVU350B
1SV271	C-Di	=1SV237:	71a(1,7mm)	Tos	-
1SV272	PIN-Di	SMD,VHF/UHF,50V,0,6pF,0,5e(470MHz)	35	Say	-
1SV273	C-Di	=1SV270:	71a(1,7mm)	Tos	-
1SV274	C-Di	=1SV262:	71a(1,3mm)	Tos	-
1SV275	C-Di	=1SV269:	71a(1,3mm)	Tos	-
1SV276	C-Di	=1SV270:	71a(1,7mm)	Tos	-
1SV277	C-Di	SMD,VHF/UHF-Tuner,10V,1,8S..2,35(4V)	71a(1,7mm)	Tos	-
1SV278	C-Di	=1SV153A:	71a(1,3mm)	Tos	-
1SV279	C-Di	=1SV212:	71a(1,3mm)	Tos	HVC351,HVE351
1SV28	PIN-Di	110V,0,05A,0,2pF,1,7GHz	-	Nec	-
1SV280	C-Di	=1SV239:	71a(1,3mm)	Tos	-
1SV281	C-Di	=1SV270:	71a(1,3mm)	Tos	HVC350B
1SV282	C-Di	=1SV262:	71a(1,3mm)	Tos	-
1SV283	C-Di	=1SV269:	71a(1,3mm)	Tos	HVC306A
1SV284	C-Di	=1SV270:	71a(1,3mm)	Tos	-
1SV285	C-Di	=1SV277:	71a(1,3mm)	Tos	HVC369B
1SV286	C-Di	=1SV224:	71a(1,3mm)	Tos	-
1SV287	C-Di	0,53..0,68pF(25V),Rs<2,3e(470MHz)	-		1SV245
1SV287	C-Di	SMD,UHF/SHF-Tuning,35V	71a(1,7mm)	Tos	MA368,MA373,HVU12,HVU314,HVU316
1SV288	C-Di	SMD,CATV-Tuning,35V,45/2,8pF(2/25V)	71a(1,7mm)	Tos	MA374,1SV302
1SV29	Si-Di	UHF-Multiplier,32V,0,7..1,1pF,11GHz	-	Nec	-
1SV290	C-Di	=1SV288:	71a(1,3mm)	Tos	1SV303
1SV291	C-Di	=1SV287:	71a(1,3mm)	Tos	-
1SV293	C-Di	18..20/10,1..11,6pF(1/4V),Rs<0,4e	-		-
1SV293	C-Di	SMD,VCOf.UHF-BandRadio,10V	71a(1,7mm)	Tos	-
1SV294	PIN-Di	SMD,VHF/UHF,50V,0,23pF,7,5e(100MHz)	35(2,9mm)	Say	-
1SV298	PIN-Di	SMD,VHF/UHF,50V,0,23pF,7,5e(100MHz)	44	Say	-
1SV30	SI-Di	UHF-Multiplier,48V,0,4..0,8pF,11GHz	Koax	Nec	-
1SV302	C-Di	SMD,CATV-Tuning,35V,47/2,6pF(2/25V)	71a(1,7mm)	Tos	MA374,1SV288
1SV303	C-Di	=1SV302:	71a(1,3mm)	Tos	1SV290
1SV304	C-Di	17,3..19,3/5,3..6,6pF(1/4V),Rs<0,32e	-		-
1SV304	C-Di	SMD,VCOf.VHF-BandRadio,10V	71a(1,7mm)	Tos	-
1SV305	C-Di	=1SV304:	71a(1,3mm)	Tos	-
1SV306	C-Di	14..16/5,5..6,5pF(2/10V),Rs<0,4e	-		-
1SV306	C-Di	SMD,Dual,VCOf.VHF-BandRadio,15V	44s2(2mm)	Tos	-
1SV308	PIN-Di	SMD,VHF-TunerBand-S,30V,1,1e(10mA)	71a(1,2mm)	Tos	-
1SV31	SI-Di	UHF-Multiplier,48V,0,8..1,2pF,11GHz	Koax	Nec	-
1SV310	C-Di	Rs<0,4e(470MHz)	-		-

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1SV310	C-Di	SMD,UHF-VCO,10V,4,45..5,45pF(4V)	71a(1,7mm)	Tos	-
1SV311	C-Di	=1SV310:	71a(1,2mm)	Tos	-
1SV313	C-Di	Rs<0,45e(470MHz)	-		-
1SV313	C-Di	SMD,UHF-VCO,10V,2,75..3,4pF(2,5V)	71a(1,7mm)	Tos	-
1SV314	C-Di	=1SV313:	71a(1,2mm)	Tos	-
1SV315	PIN-Di	50V,50mA,2,4ke(10?A),6e(10mA,100MHz)	-		-
1SV315	PIN-Di	SMD,Dual,HF-Abschwдcher/Attenuator	35o(2mm)	Say	-
1SV316	PIN-Di	50V,50mA,2,4ke(10?A),6e(10mA,100MHz)	-		-
1SV316	PIN-Di	SMD,Dual,HF-Abschwдcher/Attenuator	35o(2,9mm)	Say	-
1SV317	C-Di	Rs=0,26e(470MHz)	-		-
1SV317	C-Di	SMD,Tuning,10V,23,5/9,4pF(0,5/4V)	71a(1,7mm)	Tos	-
1SV318	C-Di	=1SV317:	71a(1,2mm)	Tos	-
1SV32	Si-Di	UHF-L,90V,7,8..10pF,350..650MHz	32a$	Nec	-
1SV322	C-Di	Rs<0,8e(100MHz)	-		-
1SV322	C-Di	SMD,TCXO/VCO,10V,6,0..7,1pF(4V)	71a(1,7mm)	Tos	-
1SV323	C-Di	=1SV322:	71a(1,2mm)	Tos	-
1SV324	C-Di	Rs<0,8e(100MHz)	-		-
1SV324	C-Di	SMD,TCXO/VCO,10V,9,2..12pF(4V)	71a(1,7mm)	Tos	-
1SV325	C-Di	=1SV324:	71a(1,2mm)	Tos	-
1SV329	C-Di	Rs<0,7e(470MHz)	-		-
1SV329	C-Di	SMD,UHF-VCO,10V,1,85..2,45pF(4V)	71a(1,7mm)	Tos	-
1SV33	Si-Di	UHF-L,90V,10..15pF,250..550MHz	32a	Nec	-
1SV330	C-Di	Rs=0,45e(470MHz)	-		-
1SV330	C-Di	SMD,TCXO/VCO,10V,18/5,1pF(1/4V)	71a(1,7mm)	Tos	-
1SV331	C-Di	=1SV330:	71a(1,2mm)	Tos	-
1SV34	PIN-Di	110V,0,05A,<0,5pF(50V),<10e(100MHz)	31a	Nec	-
1SV35	PIN-Di	110V,0,05A,<0,5pF(50V),<10e(100MHz)	31a	Nec	-
1SV36	PIN-Di	110V,0,05A,<0,6pF(50V),<10e(100MHz)	-	Nec	-
1SV37	PIN-Di	110V,0,05A,<0,6pF(50V),<10e(100MHz)	Koax	Nec	-
1SV45	Si-Di	Snap-off-Di,UHF-Multiplier,55V	Koax	Nec	-
1SV46	PIN-Di	S,65V,50mA,0,1..0,2pF,<120ns	-	Nec	-
1SV47	PIN-Di	S,65V,50mA,0,1..0,2pF,<120ns	Koax	Nec	-
1SV48	PIN-Diode	Modulator,Sw,33V,50mA,0,18..0,36pF(10V)	Koax	Nec	-
1SV48(-1,-2)	PIN-Di	-1,-2:0,09..0,18pF(10V)	-		-
1SV48(-1,-2)	PIN-Di	Modulator,S,33V,50mA,0,18..0,36pF	Koax	Nec	-
1SV48-1	PIN-Diode	Modulator,Sw,33V,50mA,0,19..0,18pF(10V)	Koax	Nec	-
1SV49	GaAs-Di	UHF-Multiplier,20V,0,15..0,4pF,18GHz	-	Nec	-
1SV50	C-Diode	FM/VHF-AFC/Tuning,30V,4,5..6pF(25V)	71a(4mm)	Nec	BB109,BB143,MV109,MV2101..2115
1SV50((1),S)	C-Di	(1),S:4,9..5,8pF(25V)	-		-
1SV50((1),S)	C-Di	FM/VHF-AFC/Tuning,30V,4,5..6pF(25V)	71a(4mm)	Nec	BB109,BB143,MV109,MV2101..2115
1SV50-1	C-Diode	FM/VHF-AFC/Tuning,30V,4,9..5,8pF(25V)	71a(4mm)	Nec	BB109,BB143,MV109,MV2101..2115
1SV50S	C-Diode	FM/VHF-AFC/Tuning,30V,4,9..5,8pF(25V)	71a(4mm)	Nec	BB109,BB143,MV109,MV2101..2115
1SV52	GaAs-Di	Schottky-Di,6V,50mA,0,1..0,22pF(0V)	-	Nec	-
1SV53(A,B)	C-Di	A:27..31pF(3V),B:29..33pF(3V)	-		-
1SV53(A,B)	C-Di	VHF-AFC,30V,27..33pF(3V)	31a	Njr	BA125,BB119,1SV114,1SV125
1SV53A	C-Diode	VHF-AFC,30V,27..31pF(3V)	31a	Njr	BA125,BB119,1SV114,1SV125
1SV53B	C-Diode	VHF-AFC,30V,29..33pF(3V)	31a	Njr	BA125,BB119,1SV114,1SV125
1SV54	C-Di	VHF-AFC,15V,26..32pF(3V)	71a(4mm)	Njr	BA125,BB119,1SV114,1SV125
1SV54G	C-Di	=1SV54:	31a	-	BA125,BB119,1SV114,1SV125
1SV55	C-Di	Dual,FM-Tuning,32V,37..42pF(3V)	7p	Hit	BB104,BB204,BB304,MV104,1SV109
1SV56	C-Di	SMD,VHF-AFC/Tuning,25V,35<50pF(1,5V)	-	Nec	-
1SV57	C-Di	SMD,VHF-AFC/Tuning,25V,15<20pF(10V)	-	Nec	-
1SV58	C-Di	VHF-Tuning,30V,2..2,5pF(25V)	71a(4mm)	Hit	BB105,BB205,BB305,BB405,BB505+
1SV59	C-Di	VHF-Tuning,30V,2..2,3pF(25V)	71a(4mm)	Hit	BB105,BB205,BB305,BB405,BB505+
1SV65	PIN-Di	S,Modulator,33V,50mA,<0,18pF,<60ns	Koax	Nec	-
1SV66	PIN-Di	S,Modulator,33V,50mA,<0,18pF,<60ns	Koax	Nec	-
1SV68	C-Di	FM/VHF-Tuning,30V,4,3..6pF(25V)	31a	Hit	BB101,BB110,BB203,MV310,1SV84
1SV69(A,B)	C-Di	A:2..2,3pF(25V),B:2,2..2,5pF(25V)	-		-
1SV69(A,B)	C-Di	VHF-Tuning,30V,2..2,5pF(25V),<1e	31a	Hit	BB105,BB205,BB305,BB405,BB505+
1SV69A	C-Diode	VHF-Tuning,30V,2..2,3pF(25V),<1Ω	31a	Hit	BB105,BB205,BB305,BB405,BB505+
1SV69B	C-Diode	VHF-Tuning,30V,2,2..2,5pF(25V),<1Ω	31a	Hit	BB105,BB205,BB305,BB405,BB505+
1SV70(A,B)	C-Di	A:2..2,2pF(25V),B:2,1..2,3pF(25V)	-		-
1SV70(A,B)	C-Di	UHF-Tuning,30V,2..2,3pF(25V)	31a	Hit	BB105,BB205,BB305,BB405,BB505+
1SV70A	C-Diode	UHF-Tuning,30V,2..2,2pF(25V)	31a	Hit	BB105,BB205,BB305,BB405,BB505+

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1SV70B	C-Diode	UHF-Tuning, 30V, 2,1..2,3pF(25V)	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV71	C-Di	AFC, 15V, 8..32pF(1V)	31a	Njr	-
1SV72	C-Di	=1SV71: 16..40pF(1V)	31a	Njr	-
1SV73	C-Di	=1SV71: 28..60pF(1V)	31a	Njr	-
1SV74	C-Di	=1SV71: 44..88pF(1V)	31a	Njr	-
1SV75	C-Di	VHF-AFC/Tuning, 30V, 4,5..6pF(25V)	71a(4mm)	Tos	BB105, BB205, BB305, BB405, BB505+
1SV76	C-Di	VHF-AFC/Tuning, 30V, 2..2,6pF(25V)	71a(4mm)	Njr	BB105, BB205, BB305, BB405, BB505+
1SV77	PIN-Di	VHF, S, 70V, 0,5pF(30V), <800ns	7d	Nec	-
1SV80	PIN-Di	VHF, 30V, 50mA, 0,4pF(15V)	31a	Nec	-
1SV81	Si-Di	VHF/UHFTV-Tuner	-	Tos	-
1SV82	PIN-Di	0,25pF(50V)	-	Tos	-
1SV84	C-Di	FM-Tuning, 30V, 2,5..3pF(25V), <1,2e	31a	Hit	BB101, BB110, BB203, MV310, 1SV68
1SV87	C-Di	VHF-Tuning, 30V, 5..7pF(25V)	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV88	C-Di	VHF-Tuning, 30V, 2,6..3pF(25V), <0,9e	71a(4mm)	Nec	BB105, BB205, BB305, BB405, BB505+
1SV89	C-Di	VHF/UHF-AFC, 34V, 3,3..5,7pF(10V)	31a	Hit	BA121, BB117, BB417
1SV90(A)	C-Di	AM-Tuning, 12(A=15)V, 400..650pF(1V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV91	C-Di	AM-Tuning, 12V, 400..550pF(1V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV92	C-Di	AM-Tuning, 12V, 400..520pF(1V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV93	C-Di	AM-Tuning, 12V, 22<30pF(9V)	7d	Hit	BB112, BB130, BB509, 1SV134..135, +
1SV94	C-Di	UHF-Tuning, 30V, 2..2,5pF(25V), <0,7e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV95	C-Di	VHF-Tuning, 30V, 11..13pF(3V), <0,85e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV96	C-Di	Dual, 30V, 41..49pF(2V)	7c	Hit	-
1SV97	C-Di	VHF-Tuning, 30V, 2,4..3pF(25V), <1,2e	31a	Hit	BB105, BB205, BB305, BB405, BB505+
1SV98	C-Di	TV/FM-Tuner-AFC, 30V, 2..2,8pF(25V)	31a	Hit	BB119, 1SV50, 1SV114, 1SV125
1SV99	PIN-Di	Band-S, 50V, 0,05A, <0,5pF, <10e	7d	Tos	-
1SX170	Si-Di	Gl, S, TV, 60V, 1,5A, <350ns	-	Tix	BY258/100, BY296..299, RGP15B, +
1SX171	Si-Di	=1SX170: 75V	-		BY258/100, BY296..299, RGP15B, +
1SX172	Si-Di	=1SX170: 100V	-		BY258/100, BY296..299, RGP15B, +
1SX173	Si-Di	=1SX170: 200V	-		BY258/200, BY296..299, RGP15D, +
1SX174	Si-Di	=1SX170: 300V	-		BY258/400, BY297..299, RGP15G, +
1SX175	Si-Di	=1SX170: 400V	-		BY258/400, BY298..299, RGP15G, +
1SZ45A	Ref-Di	6,4V, 5%, 0,25W, <n0,01%/oC	31a	Nec	BZV10, BZV27, BZX90, 1N4575, 1N4580+
1SZ46A	Ref-Di	6,4V, 5%, 0,25W, <n0,005%/oC	31a	Nec	BZV11, BZV28, BZX91, 1N4576, 1N4581+
1SZ47(A)	Ref-Di	6,4V, 5%, 0,25W, <n0,002%/oC	31a	Nec	BZV12, BZV29, BZX92, 1N4577, 1N4582+
1SZ48(A)	Ref-Di	6,4V, 5%, 0,25W, <n0,001%/oC	31a	Nec	BZV13, BZV30, BZX93, 1N4578, 1N4583+
1SZ50	Ref-Di	6,2V, 5%, 0,25W, <n0,01%/oC	31a	Nec	BZV10, BZV27, BZX90, 1N4575, 1N4580+
1SZ51	Ref-Di	6,2V, 5%, 0,25W, <n0,005%/oC	31a	Nec	BZV11, BZV28, BZX91, 1N4576, 1N4581+
1SZ52	Ref-Di	6,2V, 5%, 0,25W, <n0,002%/oC	31a	Nec	BZV12, BZV29, BZX92, 1N4577, 1N4582+
1SZ53	Ref-Di	6,2V, 5%, 0,25W, <n0,001%/oC	31a	Nec	BZV13, BZV30, BZX93, 1N4578, 1N4583+
1T	Si-N	=2SC3077 (Typ-Code/Stempel/marking)	35	Mat	→2SC3077
1T	Si-N	=2SC3933 (Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC3933
1T	Si-N	=2SC4975 (Typ-Code/Stempel/marking)	?35	Mat	→2SC4975
1T	Si-N-Darl	=2SD2416 (Typ-Code/Stempel/marking)	39	Mat	→2SD2416
1T	Si-N	=MMBT3960A (Typ-Code/Stempel/marking)	35	Mot	→MMBT3960A
1T1	Si-P	=MMST5101 (Typ-Code/Stempel/marking)	35	Rhm	→MMST5101
1T1	Si-P	=SST5101 (Typ-Code/Stempel/marking)	35	Rhm	→SST5101
1T32(A)	C-Di	SMD, VHF/UHF-Tuning, 30V, 2..2,4pF(25V)	71a(2,7mm)	Son	BB515, BB721, BB723, 1SV188, 1SV202+
1T33(A)	C-Di	SMD, CATV-Tuning, 30V, 2,7..3pF(25V)	71a(2,7mm)	Son	-
1T339	PD	780nm S=0.5mA/mW	FLAT8	Son	-
1T339	Opto	CD, Photodiode	8-MDIP	Son	-
1T33C	C-Di	SMD, CATV-Tuning, 30V, 2,4..2,8pF(28V)	71a(2,7mm)	-	-
1T359	C-Di	SMD, Radio/TV-Tuning, 30V, 4o4,8pF(25V)	71a(2,7mm)	Son	-
1T360	C-Di	=1T364:	71a(2,7mm)	Son	MA371, 1SV217
1T362	C-Di	=1T32:	71a(1,7mm)	Son	BB535, MA360, MA372, 1SV214, 1SV223
1T363	C-Di	=1T33C:	71a(1,7mm)	Son	BB639, MA355, MA366, MA371
1T364	C-Di	SMD, CATV-Tuning, 30V, 2,3..2,7pF(25V)	71a(1,7mm)	Son	MA355, MA357, MA366
1T365	C-Di	SMD, BS-Tuning, 30V, 0,6..0,77pF(25V)	71a(1,7mm)	Son	-
1T366	C-Di	SMD, TV-Tuner, 30V, >1,9pF(28V)	71a(1,7mm)	Son	-
1TH61	Si-Di	Gl, Uni, 1500V, 0,3A, <6?s	31a	Tos	BY228, DM513, EM516, GP10W..Y
1TK551	TTL Logic	NVcc:(5.0n0.25)V tpd=24ns ft=30Mc	14dil	Sov	JKFF 7472a
1TK552	TTL Logic	NVcc:(5.0n0.25)V tpd=22ns ft=22Mc	14dil	Sov	Dual FF with preset, clear 7474a
1TQ	Si-N	=2SC4773-Q (Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4773
1TR	Si-N	=2SC4773-R (Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4773
1TR551	TTL Logic	NVcc:(5.0n0.25)V tpd<35ns ft=20Mc	14dil	Sov	R/L-SR, 4-bit 7495a

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1TS	Si-N	=2SC4773-S(Typ-Code/Stempel/marking)	35(2mm)	Rhm	→2SC4773
1TZ61	Si-Di	GI,Uni,1500V,1A	31a	Tos	BY228,DM513,EM516,GP10W..Y
1U	Si-N	=2SC3110(Typ-Code/Stempel/marking)	35	Mat	→2SC3110
1U	Si-N	=2SC3934(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC3934
1U	Si-N	=KST2484(Typ-Code/Stempel/marking)	35	Sam	→KST2484
1U	Si-N	=MMBT2484(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT2484
1V	Si-N	=2SD1149(Typ-Code/Stempel/marking)	35	Mat	→2SD1149
1V	Si-N	=2SD1824(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1824
1V	Si-N	=2SD2441(Typ-Code/Stempel/marking)	39	Mat	→2SD2441
1V	Si-N	=BF820(Typ-Code/Stempel/marking)	35	Phi	→BF820
1V	Si-N	=MMBT6427(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT6427
1V-	Si-N	=BF820W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BF820W
1V01H	Si-Di	=HN1V01H(Typ-Code/Stempel/marking)	8-MDIP	Tos	→HN1V01H
1V02H	Si-Di	=HN1V02H(Typ-Code/Stempel/marking)	8-MDIP	Tos	→HN1V02H
1Vp	Si-N	=BF820(Typ-Code/Stempel/marking)	35	Phi	→BF820
1VR	Si-N	=2SD1149-R(Typ-Code/Stempel/marking)	35	Mat	→2SD1149
1VR	Si-N	=2SD1824-R(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1824
1VS	Si-N	=2SD1149-S(Typ-Code/Stempel/marking)	35	Mat	→2SD1149
1VS	Si-N	=2SD1824-S(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1824
1VT	Si-N	=2SD1149-T(Typ-Code/Stempel/marking)	35	Mat	→2SD1149
1VT	Si-N	=2SD1824-T(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1824
1Vt	Si-N	=BF820(Typ-Code/Stempel/marking)	35	Phi	→BF820
1Vt	Si-N	=BF820W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BF820W
1W	Si-P	=BF821(Typ-Code/Stempel/marking)	35	Phi	→BF821
1W	Si-N	=FMMT3903(Typ-Code/Stempel/marking)	35	Fer	→FMMT3903
1Wp	Si-P	=BF821(Typ-Code/Stempel/marking)	35	Phi	→BF821
1Wt	Si-P	=BF821(Typ-Code/Stempel/marking)	35	Phi	→BF821
1X	Si-P	=2SB1599(Typ-Code/Stempel/marking)	39	Mat	→2SB1599
1X	Si-N	=2SC2845(Typ-Code/Stempel/marking)	35	Mat	→2SC2845
1X	Si-N	=BF822(Typ-Code/Stempel/marking)	35	Phi	→BF822
1XB	Si-N	=2SC4780-B(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC4780
1XC	Si-N	=2SC4780-C(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SC4780
1Xp	Si-N	=BF822(Typ-Code/Stempel/marking)	35	Phi	→BF822
1Xt	Si-N	=BF822(Typ-Code/Stempel/marking)	35	Phi	→BF822
1Y	Si-N	=2SD2457(Typ-Code/Stempel/marking)	39	Mat	→2SD2457
1Y	Si-P	=BF823(Typ-Code/Stempel/marking)	35	Phi	→BF823
1Y	Si-N	=KST3903(Typ-Code/Stempel/marking)	35	Sam	→KST3903
1Y	Si-N	=MMBT3903(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBT3903
1Y	Si-N	=YTS3903(Typ-Code/Stempel/marking)	35	Tos	→YTS3903
1Yp	Si-P	=BF823(Typ-Code/Stempel/marking)	35	Phi	→BF823
1YQ	Si-N	=2SD2457-Q(Typ-Code/Stempel/marking)	39	Mat	→2SD2457
1YR	Si-N	=2SD2457-R(Typ-Code/Stempel/marking)	39	Mat	→2SD2457
1Yt	Si-P	=BF823(Typ-Code/Stempel/marking)	35	Phi	→BF823
1Z	Si-P	=2SB1890(Typ-Code/Stempel/marking)	39	Mat	→2SB1890
1Z	Si-N	=2SD1030(Typ-Code/Stempel/marking)	35	Mat	→2SD1030
1Z	Si-N	=2SD1823(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1823
1Z	Si-N	=2SD2345(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SD2345
1Z	Si-Di	=BAS70-06(Typ-Code/Stempel/marking)	35	Ztx	→BAS70-06
1Z	Si-N	=MMBT6517(Typ-Code/Stempel/marking)	35	Mot	→MMBT6517
1Z6,2..390(A)	Z-Di	Z,6,2..390V,10%(A=5%),1W	31a	Tos	BZW22/..,BZX61/..,ZPY..,1N5920..56,+
1ZB6,8..390	Z-Di	6,8..390V,10%,1W	31a	Tos	BZW22/..,BZX61/..,ZPY..,1N5920..56,+
1ZC12..120(A)	Z-Di	12..120V,10%(A=5%),1W	31a	Tos	BZW22/..,BZX61/..,ZPY..,1N5927..51,+
1ZF8,2..24	Z-Di	8,2..24V,5%,3W	31a	Fag	BZT03/..,BZV16/..,BZX70/..
1ZM100	Z-Di	=1ZM27:100V	31	Tos	-
1ZM180	Z-Di	=1ZM27:180V	31	Tos	-
1ZM27	Z-Di	Z,TAZ,27V,20%,1W,bidirektional	31	Tos	BZW06/..B,1N6118..6137
1ZM30	Z-Di	=1ZM27:30V	31	Tos	-
1ZM330	Z-Di	=1ZM27:330V	31	Tos	-
1ZM390	Z-Di	=1ZM27:390V	31	Tos	-
1ZM47	Z-Di	=1ZM27:47V	31	Tos	-
1ZM50	Z-Di	=1ZM27:50V	31	Tos	-
1ZQ	Si-P	=2SA1890-Q(Typ-Code/Stempel/marking)	39	Mat	→2SA1890
1ZR	Si-P	=2SA1890-R(Typ-Code/Stempel/marking)	39	Mat	→2SA1890
1ZR	Si-N	=2SD1030-R(Typ-Code/Stempel/marking)	35	Mat	→2SD1030

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1ZR	Si-N	=2SD1823-R(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1823
1ZR	Si-N	=2SD2345-R(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SD2345
1ZR	Si-N	=2SD2433-R(Typ-Code/Stempel/marking)	?35	Mat	→2SD2433
1ZS	Si-N	=2SD1030-S(Typ-Code/Stempel/marking)	35	Mat	→2SD1030
1ZS	Si-N	=2SD1823-S(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1823
1ZS	Si-N	=2SD2345-S(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SD2345
1ZS	Si-N	=2SD2433-S(Typ-Code/Stempel/marking)	?35	Mat	→2SD2433
1ZT	Si-N	=2SD1030-T(Typ-Code/Stempel/marking)	35	Mat	→2SD1030
1ZT	Si-N	=2SD1823-T(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SD1823
1ZT	Si-N	=2SD2345-T(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SD2345
1ZT	Si-N	=2SD2433-T(Typ-Code/Stempel/marking)	?35	Mat	→2SD2433
2					
2	C-Di	=1SV200(Typ-Code/Stempel/marking)	71(2,7mm)	Hit	→1SV200
2	PIN-Di	=BAR64-03W(Typ-Code/Stempel/marking)	71(1,7mm)	Sie	→BAR64-02W
2	C-Di	=BB182(Typ-Code/Stempel/marking)	71(1,3mm)	Phi	→BB182
2	C-Di	=HVC200A(Typ-Code/Stempel/marking)	71(1,3mm)	Hit	→HVC200A
2	C-Di	=HVE200A(Typ-Code/Stempel/marking)	71(1,3mm)	Hit	→HVE200A
2	C-Di	=HVR100(Typ-Code/Stempel/marking)	71(2,7mm)	Hit	→HVR100
2	C-Di	=HVU200(A)(Typ-Code/Stempel/marking)	71(1,7mm)	Hit	→HVU200(A)
2	PIN-Di	=JDP2S02S(Typ-Code/Stempel/marking)	71(1mm)	Tos	→JDP2S02S
2	Z-Di	=MAZS027(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS027
2	Si-Br	=MB2S(Typ-Code/Stempel/marking)	4-DIP	Gsi	→MB2S
2	Diode	=RB500V-40(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→RB500V-40
2,1St10	Se-St	2,1V,10mA	-	old	-
2,8St10	Se-St	2,8V,10mA	-	old	-
2.0B	Z-Di	=HZF2.0BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.0BP
2.0C	Z-Di	=HZF2.0CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.0CP
2.2B	Z-Di	=HZF2.2BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.2BP
2.2C	Z-Di	=HZF2.2CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.2CP
2.4B	Z-Di	=HZF2.4BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.4BP
2.4C	Z-Di	=HZF2.4CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.4CP
2.7B	Z-Di	=HZF2.7BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.7BP
2.7C	Z-Di	=HZF2.7CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF2.7CP
20	Z-Di	=KL3R20(Typ-Code/Stempel/marking)	71(5x2,5)	Shi	→KL3R20
20	Z-Di	=MAZS200(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS200
20	Z-Di	=MM3Z39V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
20	Si-P	=MMBT2907AW(Typ-Code/Stempel/marking)	35(2mm)	Ons	→MMBT2907AW
20	Z-Di	=U1Z20(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z20
-20	Si-N+R	=PDTC144WU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC144WU
20(X,Y,Z)	Z-Di	=U02W20V(Typ-Code/Stempel/marking)	35	Kec	→Z02W20V
200	Interface-IC	4 Single-Ended RS-232 Line Drivers With Shut-down (+5V)	200	-	V.28,RS232
200A	Z-Di	=P6SMB200A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
200PH	Z-Di	=BZD23-C200(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
200PH	Z-Di	=BZD27-C200(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
201	Si-N	=FH201(Typ-Code/Stempel/marking)	46(2mm)	Say	→FH201
201	Si-N	=FP201(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP201
201	Interface-IC	2 Single-Ended Inverting RS-232 Line Drivers/Receivers (+5V/+12V)	201	-	V.28,RS232
202	Si-N	=FH202(Typ-Code/Stempel/marking)	46(2mm)	Say	→FH202
202	Si-P+N	=FP202(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP202
202	Interface-IC	2 Single-Ended Inverting RS-232 Low Power Line Drivers/Receivers (+5V)	202	-	V.28,RS232
203	Si-N	=FH203(Typ-Code/Stempel/marking)	46(2mm)	Say	→FH203
203	Si-P+N	=FP203(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP203
203	MOS-P-FET-e*	=FX203(Typ-Code/Stempel/marking)	47	Say	→FX203
203	Interface-IC	2 Single-Ended Inverting RS-232 Low Power Line Drivers/Receivers (+5V)	203	-	V.28,RS232
204	Si-P+N	=FP204(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP204
204	Interface-IC	4 Single-Ended RS-232 Line Drivers (+5V)	204	-	V.28,RS232
205	Si-P+N	=FP205(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP205
205	MOS-P-FET-e*	=FX205(Typ-Code/Stempel/marking)	47	Say	→FX205
205	Interface-IC	5 Single-Ended Drivers and 5 Single-Ended Receivers for RS-232 (+5V)	205	-	V.28,RS232
205b	Interface-IC	5 Single-Ended Drivers and 5 Single-	205b	-	V.28,RS232
206	Si-P+N	=FP206(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP206
206	Interface-IC	4 Single-Ended Drivers and 3 Single-	206	-	V.28,RS232
206b	Interface-IC	4 Single-Ended Drivers and 3 Single-	206b	-	V.28,RS232

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207	MOS-P-FET-e*	=FX207(Typ-Code/Stempel/marking)	47	Say	→FX207
207	Interface-IC	5 Single-Ended Drivers and 3 Single-	207	-	V.28,RS232
207b	Interface-IC	5 Single-Ended Drivers and 3 Single-	207b	-	V.28,RS232
208	Si-P	=FP208(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP208
208	MOS-N-FET-e*	=FX208(Typ-Code/Stempel/marking)	47	Say	→FX208
208	Interface-IC	4 Single-Ended Drivers and 4 Single-	208	-	V.28,RS232
209	Si-N	=FP209(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP209
209	Interface-IC	3 Single-Ended Drivers and 5 Single-	209	-	V.28,RS232
20A	Z-Di	=1.5SMC20A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
20A	Z-Di	=MA3200WA(Typ-Code/Stempel/marking)	35	Mat	→MA3200WA
20A	Z-Di	=MMBZ20VA(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
20A	Z-Di	=MMQA20V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
20A	Z-Di	=P6SMB20A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
20B	Z-Di	=1PMT5920B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
20B	Z-Di	=HZF20BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF20BP
20BG2C11	Si-Di	Dual,L,S,100V,20A(Tc=102o),<800ns	23I$	Tos	BYV72-100,BYW99P-100
20BG2Z11	Si-Di	=20BG2C11:	23m$	-	-
20BL2C41	Si-Di	Dual,L,S,100V,20A,<60ns	18p$	Tos	BYV72-100,BYW99P-100
20C	Z-Di	=HZF20CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF20CP
20C	Z-Di	=P6SMB20CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
20C2R10..R30	Si-Di	=20C2S10..S30:	23m$	Sak	-
20C2S10	Si-Di	Dual,L,S,100V,16A(Tc=98o),<300ns	23I$	Sak	BYV72-100,BYW99P-100
20C2S20	Si-Di	=20C2S10:200V	23I$	-	BYV72-200,BYW99P-200
20C2S30	Si-Di	=20C2S10:300V	23I$	-	BYV74-300,MUR3030PT
20CL2C41(A)	Si-Di	Dual,L,S,150V,20A,<60ns,A:<35ns	18p$	Tos	BYV72-150,BYW99P-150
20CL2CZ41(A)	Si-Di	=20CL2C41:Iso,<35ns	17p	Tos	BYV42F-150
20CS04FM	Si-Di	Dual,Schottky,L,S,40V,20A(Tc=102o)	65p	Nec	-
20CS04FM	Si-Di	Uf<0,6V(10A),<50ns	-	-	-
20CS04M	Si-Di	=20CS04FM:	16p	-	-
20DG2C11	Si-Di	Dual,L,S,200V,20A(Tc=102o),<800ns	23I$	Tos	BYV72-200,BYW99P-200
20DG2Z11	Si-Di	=20DG2C11:	23m$	Tos	-
20DL2C41(A)	Si-Di	Dual,L,S,200V,20A,<60ns,A:<35ns	18p$	Tos	BYV72-200,BYW99P-200
20DL2C48A	Si-Di	=U20DL2C48A:	30p	Tos	→U20DL2C48A
20DL2CZ41(A)	Si-Di	=20DL2C41:Iso,<35ns	17p	Tos	BYV42F-200
20DL2CZ47A	Si-Di	Dual,L,S,200V,20A,<35ns	17p	Tos	BYV42F-200
20DL2CZ51A	Si-Di	Dual,L,S,200V,20A,<35ns	18p	Tos	BYV72F-200,BYV74F-200
20E1	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20E1..E10	Si-Di	E1=100,E2=200,E4=400,E6=600V,	-		-
20E1..E10	Si-Di	E8=800,E10=1000V	-		-
20E1..E10	Si-Di	GI,100..1000V,1,7A	31a	Inr	BYD14D..M,GP20B..M,1N5060..5062,+
20E10	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20E2	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20E2R20..R60	Si-Di	=20E2S20..S60:	23m$	Sak	-
20E2S20	Si-Di	Dual,L,S,200V,16A(Tc=85o),<300ns	23I$	Sak	BYV72-200,BYW99P-200
20E2S40	Si-Di	=20E2S20:400V	23I$	-	BYV74-400,MUR3040PT
20E2S60	Si-Di	=20E2S20:600V	23I$	-	MUR3060PT
20E4	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20E6	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20E8	Si-Di	-	31a	IRF	BYD14D..M,GP20B..M,1N5060..5062
20F	SI-N	=TSDF1220R(Typ-Code/Stempel/marking)	44	Aeg	→TSDF1220
20F2R07..R15	Si-Di	=20F2S07..S15:	23m$	Sak	-
20F2S07	Si-Di	Dual,L,S,70V,16A(Tc=109o),<250ns	23I$	Sak	BYV72-100,BYW99P-100
20F2S15	Si-Di	=20F2S07:150V	23I$	-	BYV72-150,BYW99P-150
20FL2C41A	Si-Di	Dual,L,S,300V,20A,<35ns	18p$	Tos	BYV74-300,MUR3030PT
20FL2C48A	Si-Di	=U20FL2C48A:	30p	Tos	→U20FL2C48A
20FL2CZ41A	Si-Di	=20FL2C41A:Iso	17p	-	-
20FL2CZ47A	Si-Di	Dual,L,S,300V,20A,<35ns	17p	Tos	-
20FL2CZ51A	Si-Di	Dual,L,S,300V,20A,<35ns	18p	Tos	BYV74F-300,MA655,MA695
20FWJ2C48M	Si-Di	=U20FWJ2C48M:	30p	Tos	→U20FWJ2C48M
20FWJ2CZ47M	Si-Di	Dual,Schottky,L,S,30V,20A	17p	Tos	BYV143F-35,MA752(A)
20GG2C11	Si-Di	Dual,L,S,400V,20A(Tc=102o),<800ns	23I$	Tos	BYV74-400,MUR3040PT
20GG2Z11	Si-Di	=20GG2C11:	23m$	-	-
20JG2C11	Si-Di	Dual,L,S,600V,20A(Tc=102o),<800ns	23I$	Tos	MUR3060PT
20JG2Z11	Si-Di	=20JG2C11:	23m$	-	-

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20JL2C41	Si-Di	Dual,L,S,600V,20A,<50ns	18p$	Tos	MUR3060PT
20L60	Si-Di	=DF20L60(Typ-Code/Stempel/marking)	30	Shi	→DF20L60
20LC20U	Si-Di	=DF20LC20U(Typ-Code/Stempel/marking)	30	Shi	→DF20LC20U
20LC30	Si-Di	=DF20LC30(Typ-Code/Stempel/marking)	30	Shi	→DF20LC30
20N3L	MOS-N-FET-e	=NTD20N03L27(Typ-Code/Stempel/marking)	30	Ons	→NTD20N03L27
20N60S5	MOS-N-FET-e	=SPB20N60S5(Typ-Code/Stempel/marking)	30	Sie	→SPB20N60S5
20N60S5	MOS-N-FET-e	=SPP20N60S5(Typ-Code/Stempel/marking)	17	Sie	→SPP20N60S5
20N60S5	MOS-N-FET-e	=SPW20N60S5(Typ-Code/Stempel/marking)	16	Sie	→SPW20N60S5
20PC3M	Si-Di	=DF20PC3M(Typ-Code/Stempel/marking)	30	Shi	→DF20PC3M
20PH	Z-Di	=BZD23-C20(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
20PH	Z-Di	=BZD27-C20(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
20S2S03	Si-Di	Dual,Schottky,L,S,30V,20A(Tc=81o)	23I$	Sak	(BYS28-45,BYV73-30,MBR3035PT)
20S2S03	Si-Di	Uf<0,55V(10A),<100ns	-		-
20S2S04	Si-Di	=20S2S03:40V	23I$	-	(BYS28-45,BYV73-40,MBR3045PT)
20SC4M	Si-Di	=DF20SC4M(Typ-Code/Stempel/marking)	30	Shi	→DF20SC4M
20SC9M	Si-Di	=DF20SC9M(Typ-Code/Stempel/marking)	30	Shi	→DF20SC9M
20W	Z-Di	=MA3200W(Typ-Code/Stempel/marking)	44	Mat	→MA3200W
20Y	Z-Di	=BZV49/C20(Typ-Code/Stempel/marking)	39	Val	→BZV49/C20
21	Z-Di	=MM3Z43V(Typ-Code/Stempel/marking)	71(1,7mm)	Ons	→MM3Z2V4..75V
21	Si-N/P+R	=RN47A1(Typ-Code/Stempel/marking)	45(2mm)	Tos	→RN47A1
210	Si-P	=FP210(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP210
211	Si-N	=FP211(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP211
211	Interface-IC	4Single-EndedDriversand5Single-	211	-	V.28,V.34,RS232
211b	Interface-IC	4Single-EndedDriversand5Single-	211b	-	V.28,V.34,RS232
212	Si-P+N	=FP212(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP212
212	Interface-IC	3Single-EndedDriversand5Single-	212	-	RS232,EIAS62
213	Si-P+Di+R	=FP213(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP213
213	Interface-IC	4Single-EndedDriversand5Single-	213	-	V.28,RS232
214	Si-N+Di+R	=FP214(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP214
214	Interface-IC	3Single-EndedDriversand5Single-	214	-	EIAS62,RS232
215	Si-P	=FP215(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP215
216	Si-N	=FP216(Typ-Code/Stempel/marking)	45(5mm)	Say	→FP216
216	Interface-IC	LowPowerRS-232/RS-422/EIA-562Apple	216	-	RS232,RS422,EIA562
218	Interface-IC	2Single-EndedInvertingRS-232/EIA-	218	-	EIA562,RS232
21A	Z-Di	=MMQA21V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
21B	Z-Di	=1PMT5921B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
22	Z-Di	=MAZS220(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS220
22	Si-N/P+R	=RN47A2(Typ-Code/Stempel/marking)	45(2mm)	Tos	→RN47A2
22	Si-Di	=SM-1XZ02(Typ-Code/Stempel/marking)	31	Org	→SM-1XZ02
22	Z-Di	=U1Z22(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z22
22	Z-Di	=UDZ2.4B(Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
22(X,Y,Z)	Z-Di	=U02W22V(Typ-Code/Stempel/marking)	35	Kec	→Z02W22V
220	Interface-IC	2Single-EndedInvertingRS-232LowPowerLineDrivers/Receivers(+5V)	220	-	V.24,V.28,RS232
220PH	Z-Di	=BZD23-C220(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
220PH	Z-Di	=BZD27-C220(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
222	Interface-IC	2Single-EndedInvertingLowPowerRS-232LineDrivers/Receivers(+5V)	222	-	V.28,RS232
2221..2222(A)	Si-N	=2N2221..22(A):0,625W	7a	Itt	→2N2221..22(A)
223	Interface-IC	4Single-EndedDriversand5Single-	223	-	V.28,RS232
225	Interface-IC	5Single-EndedInvertingRS-232Line	225	-	V.28,RS232
22A	Z-Di	=1.5SMC22A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
22A	Z-Di	=MMQA22V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
22A	Z-Di	=P6SMB22A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
22B	Z-Di	=1PMT5922B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
22B	Z-Di	=HZF22BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF22BP
22C	Z-Di	=F1C2200(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2200
22C	Z-Di	=HZF22CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF22CP
22C	Z-Di	=P6SMB22CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
22D	Z-Di	=F1C2230(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2230
22F	Z-Di	=F1C2250(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2250
22G	Z-Di	=F1C2260(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2260
22H	Z-Di	=F1C2270(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2270
22I	Z-Di	=F1C2280(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2280
22J	Z-Di	=F1C2290(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2290
22PH	Z-Di	=BZD23-C22(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.

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22PH	Z-Di	=BZD27-C22(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
22Y	Z-Di	=BZV49/C22(Typ-Code/Stempel/marking)	39	Val	→BZV49/C22
23	Si-P+R	=PDTA114TK(Typ-Code/Stempel/marking)	35	Phi	→PDTA114TK
23	Si-N/P+R	=RN47A3(Typ-Code/Stempel/marking)	45(2mm)	Tos	→RN47A3
-23	Si-P+R	=PDTA114TU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA114TU
230	Interface-IC	4 Single-Ended RS-232 Line Drivers With Shut-down (+5V)	230	-	V.28,RS232
231	Interface-IC	2 Single-Ended Inverting RS-232 Line Drivers/Receivers (+5V/+12V)	231	-	V.28,RS232
232	Interface-IC	2 Single-Ended Inverting RS-232 Low Power Line Drivers/Receivers (+5V)	232	-	V.28,RS232
233	Interface-IC	2 Single-Ended Inverting RS-232 Low Power Line Drivers/Receivers (+5V)	233	-	V.28,RS232
234	Interface-IC	4 Single-Ended RS-232 Line Drivers (+5V)	234	-	V.28,RS232
235	Interface-IC	5 Single-Ended Drivers and 5 Single-	235	-	V.28,RS232
235b	Interface-IC	5 Single-Ended Drivers and 5 Single-	235b	-	V.28,RS232
236	Interface-IC	4 Single-Ended Drivers and 3 Single-	236	-	V.28,RS232
236b	Interface-IC	4 Single-Ended Drivers and 3 Single-	236b	-	V.28,RS232
237	Interface-IC	5 Single-Ended Drivers and 3 Single-	237	-	V.28,RS232
238	Interface-IC	4 Single-Ended Drivers and 4 Single-	238	-	V.28,RS232
239	Interface-IC	3 Single-Ended Drivers and 5 Single-	239	-	V.28,RS232
23A	Z-Di	=F1C2300(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2300
23B	Z-Di	=1PMT5923B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
23B	Z-Di	=F1C2310(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2310
23C	Z-Di	=F1C2320(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2320
23D	Z-Di	=F1C2330(Typ-Code/Stempel/marking)	71(5x2,5)	Org	→F1C2330
24	Si-N	=2SC5004-FB(Typ-Code/Stempel/marking)	35(1,6mm)	Nec	→2SC5004
24	Z-Di	=MAZS240(Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS240
24	Si-Di	=MMBD1201(Typ-Code/Stempel/marking)	35	Nsc	→MMBD1201
24	Z-Di	=MSCT24(Typ-Code/Stempel/marking)	35	Mop	→MSCT03..24
24	Si-N+R	=PDTC114TE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC114TE
24	Si-N+R	=PDTC114TK(Typ-Code/Stempel/marking)	35	Phi	→PDTC114TK
24	Si-N/P+R	=RN47A4(Typ-Code/Stempel/marking)	45(2mm)	Tos	→RN47A4
24	Si-Di	=SM-1XZ04(Typ-Code/Stempel/marking)	31	Org	→SM-1XZ04
24	Z-Di	=U1Z24(Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z24
-24	Si-N+R	=PDTC114TU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC114TU
24(X,Y,Z)	Z-Di	=U02W24V(Typ-Code/Stempel/marking)	35	Kec	→Z02W24V
240	Interface-IC	5 Single-Ended Drivers and 5 Single-	240	-	V.28,RS232
240b	Interface-IC	5 Single-Ended Drivers and 5 Single-	240b	-	V.28,RS232
240PH	Z-Di	=BZD23-C240(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
240PH	Z-Di	=BZD27-C240(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
241	Interface-IC	4 Single-Ended Drivers and 5 Single-	241	-	V.28,RS232
241b	Interface-IC	4 Single-Ended Drivers and 5 Single-	241b	-	V.28,RS232
242	Interface-IC	2 Single-Ended Inverting Low Power RS-	242	-	V.28,RS232
243	Interface-IC	2 Single-Ended Inverting RS-232 Low	243	-	V.28,RS232
244	Interface-IC	8 Single-Ended Drivers and 10 Single-	244	-	RS232
245	Interface-IC	8 Single-Ended Drivers and 10 Single-	245	-	RS232
246	Interface-IC	8 Single-Ended Drivers and 10 Single-	246	-	RS232
247	Interface-IC	8 Single-Ended Drivers and 9 Single-	247	-	RS232
248	Interface-IC	8 Single-Ended Drivers and 8 Single-	248	-	RS232
249	Interface-IC	6 Single-Ended Drivers and 10 Single-	249	-	RS232
24A	Z-Di	=1.5SMC24A(Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
24A	Z-Di	=MMQA24V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
24A	Z-Di	=P6SMB24A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
24B	Z-Di	=1PMT5924B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
24B	Z-Di	=HZF24BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF24BP
24C	Z-Di	=HZF24CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF24CP
24C	Z-Di	=MSCT24C(Typ-Code/Stempel/marking)	35	Mop	→MSCT03C..24C
24C	Z-Di	=P6SMB24CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
24C01-2G	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-MDIP	Iss	2401..
24C01-2P	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-DIP	Iss	2401..
24C01-2S	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-SSMDIP	Iss	2401..
24C01-2Z	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-SSMDIP	Iss	2401..
24C01-3G	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-MDIP	Iss	2401..
24C01-3P	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-DIP	Iss	2401..
24C01-3S	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-SSMDIP	Iss	2401..
24C01-3Z	EEPROM-IC	CMOS, Seriell, 128x8 Bit, I?C-Bus	8-SSMDIP	Iss	2401..
24C02	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-DIP	-	2402..

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24C02-2G	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-MDIP	Iss	2402..
24C02-2P	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-DIP	Iss	2402..
24C02-2S	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-SSMDIP	Iss	2402..
24C02-2Z	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-SSMDIP	Iss	2402..
24C02-3G	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-MDIP	Iss	2402..
24C02-3P	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-DIP	Iss	2402..
24C02-3S	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-SSMDIP	Iss	2402..
24C02-3Z	EEPROM-IC	CMOS, Seriell, 256x8 Bit, I?C-Bus	8-SSMDIP	Iss	2402..
24C04	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I?C-Bus	8-DIP	-	2404..
24C04-2G	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I?C-Bus	8-MDIP	Iss	2404..
24C04-2P	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I?C-Bus	8-DIP	Iss	2404..
24C04-3G	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I?C-Bus	8-MDIP	Iss	2404..
24C04-3P	EEPROM-IC	CMOS, Seriell, 512x8 Bit, I?C-Bus	8-DIP	Iss	2404..
24C08	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, IyC-Bus	8-DIP	-	2408..
24C08-2G	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-MDIP	Iss	2408..
24C08-2P	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-DIP	Iss	2408..
24C08-2Z	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-SSMDIP	Iss	2408..
24C08-3G	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-MDIP	Iss	2408..
24C08-3P	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-DIP	Iss	2408..
24C08-3Z	EEPROM-IC	CMOS, Seriell, 1024x8 Bit, I?C-Bus	8-SSMDIP	Iss	2408..
24C16	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, IyC-Bus	8-DIP	-	2416..
24C16-2G	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, I?C-Bus	8-MDIP	Iss	2416..
24C16-2P	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, I?C-Bus	8-DIP	Iss	2416..
24C16-3G	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, I?C-Bus	8-MDIP	Iss	2416..
24C16-3P	EEPROM-IC	CMOS, Seriell, 2048x8 Bit, I?C-Bus	8-DIP	Iss	2416..
24PH	Z-Di	=BZD23-C24 (Typ-Code/Stempel/marking)	31	Phi	→BZD23-C.
24PH	Z-Di	=BZD27-C24 (Typ-Code/Stempel/marking)	72	Phi	→BZD27-C.
24R	Si-N	=?PA810T-FB (Typ-Code/Stempel/marking)	46(2mm)	Nec	→?PA810T
24Y	Z-Di	=BZV49/C24 (Typ-Code/Stempel/marking)	39	Val	→BZV49/C24
25	Z-Di	=KL3R25 (Typ-Code/Stempel/marking)	71(5x2,5)	Shl	→KL3R25
25	Z-Di	=KL3RU25 (Typ-Code/Stempel/marking)	71(5x2,5)	Shl	→KL3RU25
25	Si-N/P+R	=RN47A5 (Typ-Code/Stempel/marking)	45(2mm)	Tos	→RN47A5
25	Z-Di	=UDZ12B (Typ-Code/Stempel/marking)	71(1,7mm)	Rhm	→UDZ2.0B..36B
250	Interface-IC	2 Single-Ended RS-232 Line Drivers/Receivers for Photocoupler	250	-	RS232
250,260,303,453..	SAW-Filter	-		-	-
251	Interface-IC	2 Single-Ended RS-232 Line Drivers/Receivers for Photocoupler Interface	251	-	RS232
252	Interface-IC	2 Insulated Single-Ended RS-232 Drivers/Receivers (Complete Interface)	252	-	RS232
253	Interface-IC	Transformer Driver for Insulated RS-485 Interface	253	-	RS485
25B	Z-Di	=1PMT5925B (Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
25R	Si-N	=?PA810T-GB (Typ-Code/Stempel/marking)	46(2mm)	Nec	→?PA810T
25SC6M	Si-Di	=DF25SC6M (Typ-Code/Stempel/marking)	30	Shl	→DF25SC6M
25SP-01..10	Si-Di	Dual, 50..1000V, 25A	770	Gie	-
26	Si-Di	=MMBD1203 (Typ-Code/Stempel/marking)	35	Nsc	→MMBD1203
2610	Interface-IC	4 Universal Single-Ended Line Drivers/Receivers wit Common Enabley	2610	-	uni
2611	Interface-IC	4 Universal Single-Ended Line Drivers/Receivers wit Common Enable	2611	-	uni
2630	Interface-IC	2 Differential or 4 Single-Ended Line Drivers (RS-422 or RS-423)	2630	-	RS423,RS422
2631	Interface-IC	4 Differential RS-422 Line Drivers with Common Enable	2631	-	FED1020,V.11,RS422
2631I	Interface-IC	4 Differential EIA-644 LVDS Line Drivers with Common Enable	2631I	-	EIA644
2632	Interface-IC	4 Differential RS-422/RS-423 Line Receivers with Common Enable	2632	-	FED1020,FED1030,RS423,V.11,RS422
2632I	Interface-IC	4 Differential EIA-644 LVDS Line Receivers with Common Enable	2632I	-	EIA644
2633	Interface-IC	4 Differential RS-422/RS-423 Line Receivers with Common Enable	2633	-	FED1020,FED1030,RS423,RS422
26S10	Interface-IC	uniVcc=5VIb=45mA IoL=20mA	16dil	Fch	4DiffTcvr 2610
26S11	Interface-IC	uniVcc=5VIb=45mA IoL=20mA	16dil	Fch	4DiffTcvr 2611
27	Z-Di	=MAZS270 (Typ-Code/Stempel/marking)	71(1,3mm)	Mat	→MAZS270
27	Si-Di	=MMBD1204 (Typ-Code/Stempel/marking)	35	Nsc	→MMBD1204
27	Si-P+R	=PDTA123JEF (Typ-Code/Stempel/marking	35(1,6mm)	Phi	→PDTA123JEF
27	Z-Di	=U1Z27 (Typ-Code/Stempel/marking)	71(6,4mm)	Tos	→U1Z27
270PH	Z-Di	=BZD23-C270 (Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
270PH	Z-Di	=BZD27-C270 (Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
27925	Si-P-Darl	?BD902	17jS	Rca	→BD902
27A	Z-Di	=1.5SMC27A (Typ-Code/Stempel/marking)	71(7,9mm)	Ons	→1.5SMC6.8A..91A
27A	Z-Di	=HZM27FA (Typ-Code/Stempel/marking)	35	Hit	→HZM27FA
27A	Z-Di	=HZM27WA (Typ-Code/Stempel/marking)	35	Hit	→HZM27WA
27A	Z-Di	=MAZK270D (Typ-Code/Stempel/marking)	45	Mat	→MAZK270D

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27A	Z-Di	=MMBZ27VA(Typ-Code/Stempel/marking)	35	Ons	→MMBZ5V6A..33VA
27A	Z-Di	=MMQA27V(Typ-Code/Stempel/marking)	46	Ons	→MMQA5V6..33V
27A	Z-Di	=P6SMB27A(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8A..220A
27B	Z-Di	=1PMT5927B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
27B	Z-Di	=HZF27BP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF27BP
27C	Z-Di	=HZF27CP(Typ-Code/Stempel/marking)	71(5x2,5)	Hit	→HZF27CP
27C	Z-Di	=MMBZ27VC(Typ-Code/Stempel/marking)	35	Ons	→MMBZ27VC
27C	Z-Di	=P6SMB27CA(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→P6SMB6.8CA..220CA
27PH	Z-Di	=BZD23-C27(Typ-Code/Stempel/marking)	31	Phi	→BZD23-C..
27PH	Z-Di	=BZD27-C27(Typ-Code/Stempel/marking)	72	Phi	→BZD27-C..
27Y	Z-Di	=BZV49/C27(Typ-Code/Stempel/marking)	39	Val	→BZV49/C27
28	Si-N	=BFP280T(Typ-Code/Stempel/marking)	44	Aeg	→BFP280T
28	Si-N	=BFQ28(Typ-Code/Stempel/marking)	52	Sie	→BFQ28
28	Si-Di	=MMBD1205(Typ-Code/Stempel/marking)	35	Nsc	→MMBD1205
28	Si-N+R	=PDTC123JE(Typ-Code/Stempel/marking)	35(1,6mm)	Phi	→PDTC123JE
28	Si-N+R	=PDTC123JEF(Typ-Code/Stempel/marking	35(1,6mm)	Phi	→PDTC123JEF
-28	Si-P+R	=PDTA144WU(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTA144WU
28025	Si-N-Darl	?BD901	17j$	Rca	→BD901
29	Si-Di	=MMBD1401(Typ-Code/Stempel/marking)	35	Nsc	→MMBD1401
2906..2907(A)	Si-P	=2N2906..07(A):0,625W	7a	Itt	→2N2906..07(A)
2910	CMOS-IC	→KT8520	-	Int	KT8520,TP3020
2910[Intel]	CMOS-IC	Telecom,µ-LawCODEC	-	Int	KT8520,TP3020
2911	CMOS-IC	→KT8521	-	Int	KT8521,TP3021
2911[Intel]	CMOS-IC	Telecom,A-LawCODEC	-	Int	KT8521,TP3021
2912	CMOS-IC	→KT3040	16-DIC	Int	ETC5040,KT3040,M5912,TP3040,?A5912
2912[Intel]	CMOS-IC	Telecom,PCMCODEC-Filter	16-DIC	Int	ETC5040,KT3040,M5912,TP3040,µA5912
2916	CMOS-IC	→KT3030,KT8554	16-DIC	Int	ETC5054,KT3030,TP3054,?A3054
2916[Intel]	CMOS-IC	→KT3030,KT8554	16-DIC	Int	ETC5054,KT3030,TP3054,µA3054
2917	CMOS-IC	→KT3032,KT8557	16-DIC	Int	ETC5057,KT3032,TP3057,?A3057
2917[Intel]	CMOS-IC	→KT3032,KT8557	16-DIC	Int	ETC5057,KT3032,TP3057,µA3057
29265	CMOSLogic	Vdd:(5.0-15.0)Vtpd=125nsat5.0V	14flat	Har,Tix	4x2NAND 4011
2955(E)	MOS-P-FET-e	=MMFT2955E(Typ-Code/Stempel/marking)	48	Mot	→MMFT2955E
29B	Z-Di	=1PMT5929B(Typ-Code/Stempel/marking)	71(2mm)	Ons	→1PMT5920B..5941B
29R	MOS-N-FET-d*	=S592TR(Typ-Code/Stempel/marking)	44	Aeg	→S592T
2A	Si-N	=2SC5036(Typ-Code/Stempel/marking)	39	Mat	→2SC5036
2A	Si-N	=2SD1304(Typ-Code/Stempel/marking)	35	Mat	→2SD1304
2A	Si-P	=FMMT3906(Typ-Code/Stempel/marking)	35	Fer	→FMMT3906
2A	Si-P	=KST3906(Typ-Code/Stempel/marking)	35	Sam	→KST3906
2A	Si-Di	=MA728(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA728
2A	Si-P	=MMBT3906(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT3906
2A	Si-P	=MMBT3906T(Typ-Code/Stempel/marking)	35(1,6mm)	Ons	→MMBT3906T
2A	Si-P	=MMBT3906W(Typ-Code/Stempel/marking)	35(2mm)	Ons	→MMBT3906W
2A	Si-P	=SXT3906(Typ-Code/Stempel/marking)	39	Sie	→SXT3906
2A	Si-P	=YTS3906(Typ-Code/Stempel/marking)	35	Tos	→YTS3906
-2A	Si-P	=PMST3906(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST3906
2A4	Z-Di	=PZM2.4NBA(Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
2A7	Z-Di	=PZM2.7NB2A(Typ-Code/Stempel/marking)	35	Phi	→PZM..NB2A
2AC3T	Triac	300V,2A(Tc=70oC),Igt/Ih<40/20mA	2a	Nec	TAG200-..,T2303-..,TAG208-..
2AC5T	Triac	=2AC3T:500V	2a	-	TAG200-..,T2303-..,TAG208-..
2AC6T	Triac	=2AC3T:600V	2a	-	TAG200-..,T2303-..,TAG208-..
2AQ	Si-N	=2SD1304-Q(Typ-Code/Stempel/marking)	35	Mat	→2SD1304
2AR	Si-N	=2SC5026-R(Typ-Code/Stempel/marking)	39	Mat	→2SC5026
2AR	Si-N	=2SD1304-R(Typ-Code/Stempel/marking)	35	Mat	→2SD1304
2AS	Si-N	=2SC5026-S(Typ-Code/Stempel/marking)	39	Mat	→2SC5026
2AS	Si-N	=2SD1304-S(Typ-Code/Stempel/marking)	35	Mat	→2SD1304
2B	Si-P	=2N2907(Typ-Code/Stempel/marking)	46	Nsc	→2N2907
2B	N-FET	=2SK2593(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SK2593
2B	N-FET	=2SK374(Typ-Code/Stempel/marking)	35	Mat	→2SK374
2B	N-FET	=2SK663(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK663
2B	Si-N	=BC849B(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC849
2B	Si-N	=BC849BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2B	Si-P	=FMMT2907(Typ-Code/Stempel/marking)	35	Fer	→FMMT2907

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2B	Si-P	=KST2907(Typ-Code/Stempel/marking)	35	Sam	→KST2907
2B	Si-Di	=MA729(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA729
2B	Si-P	=MMBT2907(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBT2907
2B	Si-P	=YTS2907(Typ-Code/Stempel/marking)	35	Tos	→YTS2907
2B-	Si-N	=BC849BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2B4B41	Si-Br	100V,2A	79x3	Tos	B70C2200
2BC	Si-Di	=U2BC44(Typ-Code/Stempel/marking)	71(5x3,5)	Tos	→U2BC44
2BG2C41	Si-Di	GI,Dual,100V,2A,<1,5?s	12p	Tos	-
2BG2Z41	Si-Di	=2BG2C41:	12q	-	-
2BL4	Si-Di	=MBRS240(Typ-Code/Stempel/marking)	71(5x3,5)	Ons	→MBRS240
2BP	N-FET	=2SK2593-P(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SK2593
2BP	N-FET	=2SK374-P(Typ-Code/Stempel/marking)	35	Mat	→2SK374
2BP	N-FET	=2SK663-P(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK663
2Bp	Si-N	=BC849B(Typ-Code/Stempel/marking)	35	Phi	→BC849
2BQ	N-FET	=2SK2593-Q(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SK2593
2BQ	N-FET	=2SK374-Q(Typ-Code/Stempel/marking)	35	Mat	→2SK374
2BQ	N-FET	=2SK663-Q(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK663
2BR	N-FET	=2SK2593-R(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SK2593
2BR	N-FET	=2SK374-R(Typ-Code/Stempel/marking)	35	Mat	→2SK374
2BR	N-FET	=2SK663-R(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK663
2BR	Si-N	=BC849BR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC849R
2BS	N-FET	=2SK2593-S(Typ-Code/Stempel/marking)	35(1,6mm)	Mat	→2SK2593
2BS	N-FET	=2SK374-S(Typ-Code/Stempel/marking)	35	Mat	→2SK374
2BS	N-FET	=2SK663-S(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK663
2Bs	Si-N	=BC849B(Typ-Code/Stempel/marking)	35	Sie	→BC849
2Bs	Si-N	=BC849BW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC849W
2Bt	Si-N	=BC849B(Typ-Code/Stempel/marking)	35	Phi	→BC849
2Bt	Si-N	=BC849BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2C	MOS-P-FET-e*	=2SJ0536(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SJ0536
2C	Si-N	=BC849C(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC849
2C	Si-N	=BC849CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2C	Si-P	=FMMT-A70(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A70
2C	Si-Di	=MA732(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA732
2C	Si-P	=MMBTA70(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBTA70
2C-	Si-N	=BC849CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2Cp	Si-N	=BC849C(Typ-Code/Stempel/marking)	35	Phi	→BC849
2CR	Si-N	=BC849CR(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC849R
2Cs	Si-N	=BC849C(Typ-Code/Stempel/marking)	35	Sie	→BC849
2Cs	Si-N	=BC849CW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC849W
2Ct	Si-N	=BC849C(Typ-Code/Stempel/marking)	35	Phi	→BC849
2Ct	Si-N	=BC849CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2D	MOS-N-FET-e*	=2SK3064(Typ-Code/Stempel/marking)	35(2mm)	Mat	→2SK3064
2D	Si-N	=BC849(Typ-Code/Stempel/marking)	35	Phi	→BC849
2D	Si-N	=BC849W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2D	Si-P	=KST92(Typ-Code/Stempel/marking)	35	Sam	→KST92
2D	Si-Di	=MA784(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA784
2D	Si-P	=MMBTA92(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBTA92
2D	Si-P	=MSB92W(Typ-Code/Stempel/marking)	35(2mm)	Ons	→MSB92W
2D	Si-P	=SXTA92(Typ-Code/Stempel/marking)	39	Sie	→SXTA92
-2D	Si-P	=PMSTA92(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA92
2D4B41	Si-Br	200V,2A	79x3	Tos	B140C2200
2DG2C41	Si-Di	GI,Dual,200V,2A,<1,5?s	12p	Tos	-
2DG2Z41	Si-Di	=2DG2C41:	12q	Tos	-
2Dp	Si-N	=BC849(Typ-Code/Stempel/marking)	35	Phi	→BC849
2Dt	Si-N	=BC849W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC849W
2E	Si-N	=2SD2457(Typ-Code/Stempel/marking)	39	Mat	→2SD2457
2E	Si-P	=FMMT-A93(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A93
2E	Si-P	=KST93(Typ-Code/Stempel/marking)	35	Sam	→KST93
2E	Si-Di	=MA785(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA785
2E	Si-P	=MMBTA93(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBTA93
2E	Si-P	=SXTA93(Typ-Code/Stempel/marking)	39	Sie	→SXTA93
-2E	Si-P	=PMSTA93(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA93
2ER	Si-N	=2SD2457-R(Typ-Code/Stempel/marking)	39	Mat	→2SD2457
2ES	Si-N	=2SD2457-S(Typ-Code/Stempel/marking)	39	Mat	→2SD2457

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2EZ3,6..200D	Z-Di	3,6..200V,2W,DS=5%,D10=10%	31a	Sie	BZV16/..,BZV47/..,BZX70/..,ZY..,+
2EZ3,6..200DS..10	Z-Di	3,6..200V,2W,DS=5%,D10=10%	31a	Sie	BZV16/..BZV47/..BZX70/..ZY..
2F	Si-P	=2SB1612(Typ-Code/Stempel/marking)	39	Mat	→2SB1612
2F	Si-P	=2SB792A(Typ-Code/Stempel/marking)	35	Mat	→2SB792A
2F	Si-N	=BC850B(Typ-Code/Stempel/marking)	35	Phi,Sie	→BC850B
2F	Si-N	=BC850BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2F	Si-P	=FMMT2907A(Typ-Code/Stempel/marking)	35	Fer	→FMMT2907A
2F	Si-P	=KST2907A(Typ-Code/Stempel/marking)	35	Sam	→KST2907A
2F	Si-P	=MMBT2907A(Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT2907A
2F	Si-P	=SXT2907A(Typ-Code/Stempel/marking)	39	Sie	→SXT2907A
2F	Si-Di	=U2FWJ44N(Typ-Code/Stempel/marking)	39	Tos	→U2FWJ44N
2F	Si-P	=YTS2907A(Typ-Code/Stempel/marking)	35	Tos	→YTS2907A
-2F	Si-N	=PMST2907A(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST2907A
2F-	Si-N	=BC850BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2FBP005	Si-Br	50V,2A	33x1	-	B40C2200
2FBP01	Si-Br	100V,2A	33x1	Fag	B70C2200
2FBP02	Si-Br	200V,2A	33x1	-	B140C2200
2FBP04	Si-Br	400V,2A	33x1	-	B280C2200
2FBP06	Si-Br	600V,2A	33x1	-	B400C2200
2FBP08	Si-Br	800V,2A	33x1	-	B600C2200
2FBP10	Si-Br	1000V,2A	33x1	-	B800C2200
2FL20U	SI-Di	=D2FL20U(Typ-Code/Stempel/marking)	71(8mm)	Shi	→D2FL20U
2FL40	Si-Di	=D2FL40(Typ-Code/Stempel/marking)	71(8mm)	Shi	→D2FL40
2Fp	Si-N	=BC850B(Typ-Code/Stempel/marking)	35	Phi	→BC850B
2FQ	Si-P	=2SB1583-Q(Typ-Code/Stempel/marking)	?35	Mat	→2SB1583
2FR	Si-P	=2SB1583-R(Typ-Code/Stempel/marking)	?35	Mat	→2SB1583
2FR	Si-P	=2SB792AR(Typ-Code/Stempel/marking)	35	Mat	→2SB792A
2FR	Si-N	=BC850BR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC850R
2FS	Si-P	=2SB1583-S(Typ-Code/Stempel/marking)	?35	Mat	→2SB1583
2FS	Si-P	=2SB792AS(Typ-Code/Stempel/marking)	35	Mat	→2SB792A
2Fs	Si-N	=BC850B(Typ-Code/Stempel/marking)	35	Sie	→BC850B
2Fs	Si-N	=BC850BW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC850W
2FS4	Si-Di	=D2FS4(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→D2FS4
2FS6	Si-Di	=D2FS6(Typ-Code/Stempel/marking)	71(7,6x4)	Shi	→D2FS6
2Ft	Si-N	=BC850B(Typ-Code/Stempel/marking)	35	Phi	→BC850
2Ft	Si-N	=BC850BW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2Ft	Si-N	=BC850C(Typ-Code/Stempel/marking)	35	Phi	→BC850
2FV20	Si-Di	=D2F20(Typ-Code/Stempel/marking)	71(8mm)	Shi	→D2F20
2FV60	SI-Di	=D2F60(Typ-Code/Stempel/marking)	71(8mm)	Shi	→D2F60
2FWJ42	Si-Di	Schottky-Gl,30V,2A,<35ns	31a	Tos	-
2G	Si-N	=BC850C(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC850
2G	Si-N	=BC850CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2G	Si-P	=FMMT-A56(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A56
2G	Si-P	=KST56(Typ-Code/Stempel/marking)	35	Sam	→KST56
2G	Si-P	=MMBTA56(Typ-Code/Stempel/marking)	35	Mot,Sam,Nsc	→MMBTA56
-2G	Si-P	=PMSTA56(Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA56
2G-	Si-N	=BC850CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2G4B41	Si-Br	400V,2A	79x3	Tos	B280C2200
2GC	Si-Di	=U2GC44(Typ-Code/Stempel/marking)	71(5x3,5)	Tos	→U2GC44
2GG2C41	Si-Di	Gl,Dual,400V,2A,<1,5?s	12p	Tos	-
2GG2Z41	Si-Di	=2GG2C41:	12q	-	-
2GM	Si-P	=MMBTA56(Typ-Code/Stempel/marking)	35	Mot	→MMBTA56
2GR	Si-N	=BC850CR(Typ-Code/Stempel/marking)	35	Sie,Phi	→BC850R
2Gs	Si-N	=BC850CW(Typ-Code/Stempel/marking)	35(2mm)	Sie	→BC850W
2Gt	Si-N	=BC850CW(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2GT	Si-P	=S0A56(Typ-Code/Stempel/marking)	35	Tho	→S0A56
2GWJ2C42	Si-Di	=U2GWJ2C42:	30p	Tos	→U2GWJ2C42
2GWJ42	Si-Di	Schottky-Gl,40V,2A,<35ns	31a	Tos	-
2H	Si-N	=BC850(Typ-Code/Stempel/marking)	35	Phi	→BC850
2H	Si-N	=BC850W(Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2H	Si-P	=FMMT-A55(Typ-Code/Stempel/marking)	35	Fer	→FMMT-A55
2H	Si-P	=KST55(Typ-Code/Stempel/marking)	35	Sam	→KST55
2H	SI-Di	=MA2ZD02(Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA2ZD02
2H	Si-P	=MMBTA55(Typ-Code/Stempel/marking)	35	Mot,Sam	→MMBTA55

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-2H	Si-P	=PMSTA55 (Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMSTA55
2H3	Si-Di	=M2FH3 (Typ-Code/Stempel/marking)	71(5x3,75)	Shi	→M2FH3
2Hp	Si-N	=BC850 (Typ-Code/Stempel/marking)	35	Phi	→BC850
2Ht	Si-N	=BC850W (Typ-Code/Stempel/marking)	35(2mm)	Phi	→BC850W
2HT	Si-P	=S0A55 (Typ-Code/Stempel/marking)	35	Tho	→S0A55
2I	Si-N	=2SD2474 (Typ-Code/Stempel/marking)	39	Mat	→2SD2474
2J	Si-P	=MMBT3640 (Typ-Code/Stempel/marking)	35	Mot,Nsc	→MMBT3640
2J4B41	Si-Br	600V,2A	79x3	Tos	B400C2200
2JC	Si-Di	=U2JC44 (Typ-Code/Stempel/marking)	71(5x3,5)	Tos	→U2JC44
2JG2C41	Si-Di	Gl,Dual,600V,2A,<1,5?s	12p	Tos	-
2JG2Z41	Si-Di	=2JG2C41:	12q	-	-
2K	Si-P	=2SB1614 (Typ-Code/Stempel/marking)	39	Mat	→2SB1614
2K	Si-Di	=MA2Z748 (Typ-Code/Stempel/marking)	71(1,7mm)	Mat	→MA2Z748
2KBP005(M)	Si-Br	Gl-Br,50V,2A	33x1	Gie	B35C2000
2KBP01(M)	Si-Br	Gl-Br,100V,2A	33x1	Gie	B70C2000
2KBP01..10	Si-Br	50..1000V,2A	33(+??-)	Gie	B30..500C2200
2KBP02(M)	Si-Br	Gl-Br,200V,2A	33x1	Gie	B140C2000
2KBP04(M)	Si-Br	Gl-Br,400V,2A	33x1	Gie	B280C2000
2KBP06(M)	Si-Br	Gl-Br,600V,2A	33x1	Gie	B420C2000
2KBP08(M)	Si-Br	Gl-Br,800V,2A	33x1	Gie	B560C2000
2KBP10(M)	Si-Br	Gl-Br,1000V,2A	33x1	Gie	B700C2000
2L	Si-P	=KST5401 (Typ-Code/Stempel/marking)	35	Sam	→KST5401
2L	Si-P	=MMBT5401 (Typ-Code/Stempel/marking)	35	Mot,Nsc,Sam	→MMBT5401
-2L	Si-P	=PMST5401 (Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST5401
2M	MOS-N-FET-e	=2SK2211 (Typ-Code/Stempel/marking)	39	Mat	→2SK2211
2M	Si-P	=FMMT5087 (Typ-Code/Stempel/marking)	35	Fer	→FMMT5087
2M	Si-N	=MMBT404 (Typ-Code/Stempel/marking)	35	Mot	→MMBT404
2M3	Si-Di	=M2FM3 (Typ-Code/Stempel/marking)	71(5x3,75)	Shi	→M2FM3
2N	Si-N-Darl	=2SD1478 (Typ-Code/Stempel/marking)	35	Mat	→2SD1478
2N	Si-P	=MMBT404A (Typ-Code/Stempel/marking)	35	Mot	→MMBT404A
2N0	Si-N	=ZXT11N20DF (Typ-Code/Stempel/marking)	35	Ztx	→ZXT11N20DF
2N02	MOS-N-FET-e	=ZXM62N02E6 (Typ-Code/Stempel/marking)	46	Ztx	→ZXM62N02E6
2N02L	MOS-N-FET-e	=MMFT2N02EL (Typ-Code/Stempel/marking)	48	Mot	→MMFT2N02EL
2N03	MOS-N-FET-e	=ZXM62N03E6 (Typ-Code/Stempel/marking)	46	Ztx	→ZXM62N03E6
2N0608	MOS-N-FET-e	=SPB80N06S2-08 (Typ-Code/Stempel/mark)	30	Sie	→SPB80N06S2-08
2N0615	MOS-N-FET-e	=SPD30N60S2-15 (Typ-Code/Stempel/mark)	30	Sie	→SPD30N60S2-15
2N06L05	MOS-N-FET-e	=SPB80N06S2L-05 (Typ-Code/Stempel/mark)	30	Sie	→SPB80N06S2L-05
2N06L07	MOS-N-FET-e	=SPP80N06S2L-07 (Typ-Code/Stempel/mark)	17	Sie	→SPP80N06S2L-07
2N06L13	MOS-N-FET-e	=SPD30N06S2L-13 (Typ-Code/Stempel/mark)	30	Sie	→SPB80N06S2L-..
2N06L23	MOS-N-FET-e	=SPD30N06S2L-23 (Typ-Code/Stempel/mark)	30	Sie	→SPB80N06S2L-..
2N0807	MOS-N-FET-e	=SPB80N08S2-07 (Typ-Code/Stempel/mark)	30	Sie	→SPB80N08S2-07
2N08L07	MOS-N-FET-e	=SPP80N08S2L-07 (Typ-Code/Stempel/mark)	17	Sie	→SPP80N08S2L-07
2N100	Ge-N	NF/HF,25V,5mA,0,025W,5MHz	?1a	Bog	(AC127,ASY28..29,2SD30)
2N1000	Ge-N	NF/S,40V,0,15W,>7MHz,<-/1?s	2a	USA	-
2N1003	Ge-P	HF,35V,0,12W,	2a	Mot	AF124..127,AF200
2N1004	Ge-P	HF,35V,0,12W,	2a	Mot	AF124..127,AF200
2N1005	Si-N	Uni,15V,0,025A,0,15W,B>20	2a	Sty	BC168,BC183,BC238,BC548,2SD767+
2N1006	Si-N	=2N1005: B>45	2a	-	BC168,BC183,BC238,BC548,2SD767+
2N1007	Ge-P	NF-L,40V,3A,30W	23a$	USA	AD149,AUY19..20,2N1529..48,+
2N1008	Ge-P	NF/S,20/20/15V,0,3A,0,2W	2a	USA,Mot	AC125..126,AC151,2N1191..94
2N1008A	Ge-P	=2N1008: 40/40/15V	2a	-	ASY48,ASY77,2N1191..94
2N1008B	Ge-P	=2N1008: 60/60/15V	2a	-	ASY48,ASY77
2N1009	Ge-P	NF/S,35V,0,3A,0,15W,0,5MHz	2a	USA	AC128,AC152..153
2N101(/13)	Ge-P	NF-L,30V,Ueb=1SV,1,5A,0,4MHz	?37	USA	-
2N1010	Ge-N	HF,10/10/10V,2mA,0,02W,2MHz	2a	USA	-
2N1011	Ge-P	NF/S-L,80/40/40V,5A,90W	23a$	USA,Mot	AL102..103,AUY28,2N3615..18,+
2N1012	Ge-N	S,40/22/35V,0,15W,>3MHz,<150/200ns	2a&	USA	-
2N1013	Ge-P	S-L,60V,Ueb=30V	-	Sol	-
2N1014	Ge-P	NF/S-L,100/65/60V,5A,50W	23a$	USA	AL102..103,AUY28,2N3616,2N3618,+
2N1015(A..F)	Si-N	NF/S-L,30..300V,7,5A,150W	-	USA	-
2N1015(A..F)	Si-NPN	AF,Sw-Pow,30..300V,7,5A,150W,B>10	-	USA	-
2N1016(A..F)	Si-N	NF/S-L,30..300V,7,5A,150W	-	USA	-
2N1016(A..F)	Si-NPN	AF,Sw-Pow,30..300V,7,5A,150W,B>10	-	USA	-
2N1017	Ge-P	NF,30V,1A,0,2W	2a	USA	AC128,AC153,2SB324,2SB415

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2N1018	Ge-P	NF,30V,1A,0,2W	2a	USA	AC128,AC153,2SB324,2SB415
2N1019	-Darl	30V,3A,10W,B=15000	-	Adv	-
2N102(/13)	Ge-N	NF-L,25V,Ueb=15V,1,5A,0,4MHz	?37	USA	-
2N1020	-Darl	30V,3A,10W,B=15000	-	Adv	-
2N1021(A)	Ge-P	NF/S-L,100V,7A,150W	23a$	USA,Mot,Tix	2N1552,2N1556,2N1560,2N3616,2N3618
2N1022(A)	Ge-P	=2N1021:120V	23a$	USA,Mot,Tix	2N2290,2N2293
2N1023	Ge-P	HF,40V,10mA,0,12W,120MHz	4g	Cen	AF106,AF109R,AF306
2N1024	Si-P	Uni,18V,0,1A,0,25W,>1MHz	2a	USA	BC213,BC258,BC308,BC558,+
2N1025	Si-P	Uni,40V,0,1A,0,25W,>1MHz	2a	USA	BC212,BC257,BC307,BC557,+
2N1026(A)	Si-P	Uni,40V,0,1A,0,25W,>2MHz	2a	USA	BC212,BC257,BC307,BC557,+
2N1027	Si-P	Uni,18V,0,1A,0,25W,>4MHz	2a	USA	BC213,BC258,BC308,BC558,+
2N1028	Si-P	Uni,12V,0,1A,0,25W,>7,2MHz	2a	USA	BC213,BC258,BC308,BC558,+
2N1029	Ge-P	NF/S-L,50V,15A,90W,B>20	23a$	USA	2N1550..52,2N1555..56,2N1559..60,+
2N1029A	Ge-P	=2N1029:60V	23a$	-	2N1550..52,2N1555..56,2N1559..60,+
2N1029B	Ge-P	=2N1029:90V	23a$	-	2N1552,2N1556,2N1560
2N1029C	Ge-P	=2N1029:100V	23a$	-	2N1552,2N1556,2N1560
2N103	Ge-N	NF,35V,0,01A,0,05W,0,75MHz	?1a	Csr,Etc	AC127,ASY28,2SD30
2N1030	Ge-P	NF/S-L,50V,15A,90W,B>50	23a$	USA	2N1550..52,2N1555..56,2N1559..60,+
2N1030A	Ge-P	=2N1030:60V	23a$	-	2N1550..52,2N1555..56,2N1559..60,+
2N1030B	Ge-P	=2N1030:90V	23a$	-	2N1552,2N1556,2N1560
2N1030C	Ge-P	=2N1030:100V	23a$	-	2N1552,2N1556,2N1560
2N1031	Ge-P	NF/S-L,50V,15A,90W,B>20	23a$	USA	2N1550..52,2N1555..56,2N1559..60,+
2N1031A	Ge-P	=2N1031:60V	23a$	-	2N1550..52,2N1555..56,2N1559..60,+
2N1031B	Ge-P	=2N1031:90V	23a$	-	2N1552,2N1556,2N1560
2N1031C	Ge-P	=2N1031:100V	23a$	-	2N1552,2N1556,2N1560
2N1032	Ge-P	NF/S-L,50V,15A,90W,B>50	23a$	USA	2N1550..52,2N1555..56,2N1559..60,+
2N1032A	Ge-P	=2N1032:60V	23a$	-	2N1550..52,2N1555..56,2N1559..60,+
2N1032B	Ge-P	=2N1032:90V	23a$	-	2N1552,2N1556,2N1560
2N1032C	Ge-P	=2N1032:100V	23a$	-	2N1552,2N1556,2N1560
2N1034	Si-P	NF,50V,0,05A,0,25W,a>9	2a	USA	BC212,BC257,BC307,BC557,+
2N1035	Si-P	NF,50V,0,05A,0,25W,a>18	2a	USA	BC212,BC257,BC307,BC557,+
2N1036	Si-P	NF,50V,0,05A,0,25W,a>36	2a	USA	BC212,BC257,BC307,BC557,+
2N1037	Si-P	NF,50V,0,05A,0,25W,a>9	2a	USA	BC212,BC257,BC307,BC557,+
2N1038	Ge-P	NF/S-L,40V,3A,20W(Tc=25o)	2a$	USA,Mot,Tix	2N2564
2N1038-1	Ge-P	=2N1038:	2a$o	-	2N2552,2N2560
2N1038-2	Ge-P	=2N1038:	2a$o	-	2N1042,2N2556
2N1039	Ge-P	NF/S-L,60V,3A,20W(Tc=25o)	2a$	USA,Mot,Tix	2N2565
2N1039-1	Ge-P	=2N1039:	2a$o	-	2N2553,2N2561
2N1039-2	Ge-P	=2N1039:	2a$o	-	2N1043,2N2557
2N104	Ge-P	NF,30V,Ueb=12V,0,05A,0,15W,0,7MHz	1a	USA	AC125..126,AC151,2SB54,2SB56
2N1040	Ge-P	NF/S-L,80V,3A,20W(Tc=25o)	2a$	USA,Mot,Tix	2N2566
2N1040-1	Ge-P	=2N1040:	2a$o	-	2N2554,2N2562
2N1040-2	Ge-P	=2N1040:	2a$o	-	2N1044,2N2558
2N1041	Ge-P	NF/S-L,100V,3A,20W(Tc=25o)	2a$	USA,Mot,Tix	2N2567
2N1041-1	Ge-P	=2N1041:	2a$o	-	2N2555,2N2563
2N1041-2	Ge-P	=2N1041:	2a$o	-	2N1045,2N2559
2N1042	Ge-P	NF/S-L,40V,3,5A,20W(Tc=25o)	2a$o	USA,Mot,Tix	2N1038,2N2556
2N1042-1	Ge-P	=2N1042:	2a$o	-	2N2552,2N2560
2N1042-2	Ge-P	=2N1042:	2a$	-	2N1038,2N2564
2N1043	Ge-P	NF/S-L,60V,3,5A,20W(Tc=25o)	2a$o	USA,Mot,Tix	2N1039,2N2557
2N1043-1	Ge-P	=2N1043:	2a$o	-	2N2553,2N2561
2N1043-2	Ge-P	=2N1043:	2a$	-	2N1039,2N2565
2N1044	Ge-P	NF/S-L,80V,3,5A,20W(Tc=25o)	2a$o	USA,Mot,Tix	2N1040,2N2558
2N1044-1	Ge-P	=2N1044:	2a$o	-	2N2554,2N2562
2N1044-2	Ge-P	=2N1044:	2a$	-	2N1040,2N2566
2N1045	Ge-P	NF/S-L,100V,3,5A,20W(Tc=25o)	2a$o	USA,Mot,Tix	2N1041,2N2559
2N1045-1	Ge-P	=2N1045:	2a$o	-	2N2555,2N2563
2N1045-2	Ge-P	=2N1045:	2a$	-	2N1041,2N2567
2N1046	Ge-P	NF/S-L,100V,12A,50W	23a$	USA	2N1552,2N1556,2N1560
2N1046A,B	Ge-P	=2N1046:130V	23a$	-	AUY38,2N2527..28
2N1047(A...C)	Si-N	NF/S-L,80V,8A,40W,50MHz,B>12	-	USA,Tix	(MJE15028,MJE15030,2SC3254..55)
2N1047(A..C)	Si-NPN	AF,Sw-Pow,80V,8A,40W,50MHz,B>12	-	USA,Tix	(MJE15028,MJE15030,2SC3254..55)
2N1048(A...C)	Si-N	=2N1047:120V	-	USA,Tix	(MJE15028,MJE15030,2SC2527)
2N1048(A..C)	Si-NPN	=2N1047:120V	-	USA,Tix	(MJE15028,MJE15030,2SC2527)

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2N1049(A...C)	Si-N	NF/S-L, 80V, 8A, 40W, 50MHz, B>30	-	USA,Tix	(MJE15028,MJE15030,2SC32S4..55)
2N1049(A..C)	Si-NPN	AF,Sw-Pow,80V,8A, 40W, 50MHz, B>30	-	USA,Tix	(MJE15028,MJE15030,2SC3254..55)
2N105	Ge-P	NF,25V,0,015A,0,035W,0,75MHz	37a	USA	AC125..126,AC151,2SB54,2SB56
2N1050(A...C)	Si-N	=2N1049:120V	-	USA,Tix	(MJE15028,MJE15030,2SC2527)
2N1050(A..C)	Si-NPN	=2N1049:120V	-	USA,Tix	(MJE15028,MJE15030,2SC2527)
2N1051	Si-N	NF,60V,0,1A,0,5W,3MHz	2a$	SSi,Sty	BC174,BC182,BC190,BC546,+
2N1052	Si-N	S,180V,0,2A,0,6W,4MHz	2a$	USA	BF258..259,BF658..659,2N5058..59
2N1053	Si-N	=2N1052:200V	2a$	USA	BF258..259,BF658..659,2N5058..59
2N1054	Si-N	=2N1052:125V	2a$	USA	BF257..259,BF657..659,2N5058..59
2N1055	Si-N	=2N1052:100V	2a$	USA	BF257..259,BF657..659,2N5058..59
2N1056	Ge-P	NF/S,70V,0,3A,0,24W	2a$	USA	ASY48,ASY77,2N2042..43
2N1057	Ge-P	NF/S,45V,0,3A,0,24W	2a$	USA	ASY48,ASY76..77,2SB405ST
2N1058	Ge-N	NF/S,-/20V,0,05A,0,05W	?1a	Etc	AC127,ASY28,ASY73..75
2N1059	Ge-N	NF/S,40V,0,1A,0,18W	?1a	Etc	AC127,ASY28,ASY73..75
2N106	Ge-P	NF,15V,0,01A,0,1W,0,8MHz	?1a	USA	AC125..126,AC151,2SB54,2SB56
2N1060	Si-N	S,40V,0,2A,0,25W,<50/-ns	2a$	Wes	BSW41,BSY63,2N708.2N4123,+
2N1065	Ge-P	HF/S,40V,0,12W,>20MHz	2a	Cen,Sty	ASY76..77
2N1066	Ge-P	HF,40V,10mA,0,12W,120MHz	5g	Cen,Phi	AF106,AF109R,AF306
2N1067	Si-N	NF/S-L,60V,0,5A,5W,1,5MHz	2a$	USA	(BD137,BD167,BD525,BD825,++)
2N1068	Si-N	=2N1067:1,5A,10W	2a$	USA	(BD137,BD167,BD525,BD825,++)
2N1069	Si-N	NF/S-L,60V,4A,50W	23a$	USA	BD245A,BDV91,2N4914..15,2N5068..69+
2N107	Ge-P	NF,12V,0,01A,0,05W,1MHz	1a&	USA	AC125..126,AC151,2SB54,2SB56
2N1070	Si-N	NF/S-L,60V,4A,50V	23a$	USA	BD245A,BDV91,2N4914..15,2N5068..69+
2N1072	Si-N	NF/S,-/30V,2A(ss),12W	?2a	Sty	(BD135,BD165,BD509,BD825,++)
2N1073	Ge-P	NF/S-L,40V,10A,85W	23a$	USA,Mot	AL100..101,AUY21,2N3611..18,+
2N1073A	Ge-P	=2N1073:80V	23a$	-	AL100..101,AUY37,2N3615..18,+
2N1073B	Ge-P	=2N1073:120V	23a$	-	AL100,AUY38,2N2290,2N2293
2N1074	Si-N	NF,50V,0,05A,0,25W,a=14	2a	Ray,Sty	BC167,BC182,BC237,BC547,+
2N1075	Si-N	=2N1074:a=25	2a	Ray,Sty	BC167,BC182,BC237,BC547,+
2N1076	Si-N	=2N1074:a=50	2a	Ray,Sty	BC167,BC182,BC237,BC547,+
2N1077	Si-N	=2N1074:a=18	2a	Ray,Sty	BC167,BC182,BC237,BC547,+
2N1078	Ge-P	NF/S-L,60V,3A,20W	-	USA	-
2N1079	Si-N	NF/S-L,60V,3A,60W	-	USA	2N1722..23,(BD241A,BD535,BD935,++)
2N108	Ge-P	NF,20V,0,015A,0,05W	?2a&	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N1080	Si-N	NF/S-L,60V,3A,60W	-	USA	2N1722..23,(BD241A,BD535,BD935,++)
2N1081	Si-N	NF/S,40V,0,75A,0,6W	2a$	Tra	BC140..141,BC300..302,2N3053,+
2N1082	Si-N	Uni,25V,0,05A,0,2W,>17MHz	2a	Tra	BC168,BC183,BC238,BC548,+
2N1084	Si-P	NF,60V,2A,5W(Tc=100o)	2a$	USA	BC461,BCX60,2N4235..36
2N1085	Si-N	NF,60V,2A,5W(Tc=100o)	2a$	USA	BC441,BCX40,2N4238..39
2N1086(A)	Ge-N	NF/HF,9V,0,02A,0,065W,8MHz	?1a	USA	-
2N1087	Ge-N	NF/HF,9V,0,02A,0,065W,8MHz	?1a	USA	-
2N109	Ge-P	NF,35V,0,15A,Ueb=12V,0,165W	1a	USA	AC125..126,AC151,2SB54,2SB56
2N109/5	Ge-P	NF,25V,Ueb=12V,0,07A,0,15W	2a	Syl	AC125..126,AC151,2SB54,2SB56
2N1090	Ge-N	NF/S,25V,0,4A,0,12W,7MHz	2a	USA	ASY73..75
2N1091	Ge-N	NF/S,25V,0,4A,0,12W,13MHz	2a	USA	ASY73..75
2N1092	Si-N	NF/S,60V,0,5A,1,5MHz	2a$	USA	BC140..141,BC300..302,2N1613,+
2N1093	Ge-P	NF/S,30V,0,3A,0,15Wz	2a&	USA	AC125..126,AC151..152,2SB324
2N1094	Ge-P	UHF,30V,0,04A,0,15W,645MHz	2a$	Whs	AF139,AF239S
2N1095	Si-N	NF/S,60V,0,5W,3MHz	?1a	USA	BC140..141,BC300..302,2N3053,+
2N1096	Si-N	NF/S,90V,0,5W,3MHz	?1a	USA	BC141,BC300..301,2N1889..90,+
2N1097	Ge-P	NF,-/16V,0,1A,0,14W,B>34	2a&	USA	AC125..126,AC151,2SB54,2SB56
2N1098	Ge-P	=2N11097:B>25	2a&	USA	AC125..126,AC151,2SB54,2SB56
2N1099	Ge-P	NF/S-L,80V,15A,170W	38a$	USA,Mot	2N1982,2N2075,2N2079,2N2492..93,+
2N110	Ge-P	S,50V,Ueb=50V,0,04A,0,2W,5MHz	?1a	Wes	-
2N1100	Ge-P	=2N1099:100V	38a$	USA,Mot	2N2493
2N1101	Ge-N	NF,20V,0,1A,0,18W	?1a	USA	AC127,ASY28..29,ASY73..75
2N1102	Ge-N	=2N1101:40V	?1a	USA	-
2N1103	Si-N	NF/S,45V,0,02A,0,125W,>10MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N1104	Si-N	NF/S,45V,0,02A,0,125W,>20MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N1105	Si-N	NF,60V,0,5A,0,8W	2a$	USA	BC140..141,BC300..302,2N3053,+
2N1106	Si-N	=2N1105:100V	2a$	USA	BC141,BC300,2N1889..90,2N1990,+
2N1107	Ge-P	HF,16V,5mA,0,03W,40MHz	?1a	USA	AF124..126,AF200
2N1108	Ge-P	HF,16V,5mA,0,03W,35MHz	?1a	USA	AF124..126,AF200
2N1109	Ge-P	HF,16V,5mA,0,03W,35MHz	?1a	USA	AF124..126,AF200

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2N111(A)	Ge-P	HF,30/20V,0,2A,0,13W,3MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N1110	Ge-P	HF,16V,5mA,0,03W,35MHz	?1a	USA	AF124..126,AF200
2N1111(A,B)	Ge-P	HF,20V,5mA,0,03W,35MHz	?1a	USA	AF124..126,AF200
2N1114	Ge-N	NF/S,25V,0,2A,0,15W,>7MHz	2a&	USA	AC127,ASY28..29,ASY73..75
2N1115(A)	Ge-P	NF/S,20V,0,125A,0,15W,>5MHz	1a&	USA	AC125..126,AC151,ASY26..27
2N1116	Si-N	NF/S,60V,0,8A,0,6W(Ta=100o),>6MHz	2a$	USA	BC140..141,BC300..302,2N3053,+
2N1117	Si-N	NF/S,60V,0,8A,0,6W(Ta=100o),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053,+
2N1118(A)	Si-P	Uni,25V,0,05A,0,15W	2a$	USA	BC213,BC258,BC308,BC558,+
2N1119	Si-P	Uni,10V,0,05A,0,15W	2a$	USA	BC213,BC258,BC308,BC558,+
2N112(A)	Ge-P	HF,30V,Ueb=20V,0,2A,0,13W,5MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N1120	Ge-P	NF/S-L,80V,15A,90W	23a$	USA,Mot	2N1551..52,2N1555..56,2N1559..60
2N1121	Ge-N	HF,-/15V,0,02A,0,065W,8MHz	?1a	USA	-
2N1122	Ge-P	HF/S/Chopper,12V,0,05A,0,025W	37d	Spr,Ssi	-
2N1122A	Ge-P	=2N1122:15V	37d	-	-
2N1123	Ge-P	NF/S,45V,0,5A,0,75W	37d$o	USA	(2N1189..90)
2N1124	Ge-P	NF/S,40V,0,25A,0,3W	2a	USA	2N1189..90,2SB405ST
2N1125	Ge-P	NF/S,40V,0,25A,0,3W	2a*	USA	2N1189..90,2SB405ST
2N1126	Ge-P	=2N1124:1W	2a*o	USA	(2N1189..90,2SB405ST)
2N1127	Ge-P	=2N1125:1W	2a*o	USA	(2N1189..90,2SB405ST)
2N1128	Ge-P	NF,25V,0,25A,0,15W	2a	USA	AC128,AC152..153,AC188,2SB324
2N1129	Ge-P	NF,25V,0,25A,0,15W	2a	USA	AC128,AC152..153,AC188,2SB324
2N113	Ge-P	HF,30V,Ueb=20V,0,2A,0,13W,10MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N1130	Ge-P	NF,30V,0,25A,0,15W	2a	USA	AC128,AC152..153,AC188,2SB324
2N1131	Si-P	NF/S,50V,0,6A,0,6W,>50MHz	2a$	USA,EUR	BC161,BC303..304,2N2904..05(A),+
2N1131A,AS	Si-P	=2N1131:60V	2a$	-	BC161,BC303..304,2N2904..05(A),+
2N1132	Si-P	NF/S,50V,0,6A,0,6W,>60MHz	2a$	USA,EUR	BC161,BC303..304,2N2904..05(A),+
2N1132A	Si-P	=2N1132:60V	2a$	-	BC161,BC303..304,2N2904..05(A),+
2N1132B	Si-P	=2N1132:75V	2a$	-	BC303,BSW40,2N4031,2N4033,+
2N1135(A)	Si-P	Uni,12/12/12V,0,05A,0,1A,>5,6MHz	2a	Phc	(BC213,BC258,BC308,BC558,+
2N1136	Ge-P	NF/S-L,60V,6A,60W,B>50	23a$	USA	AL102..103,AUY28,2N3615..18,+
2N1136A	Ge-P	=2N1136:90V	23a$	-	AL102..103,AUY28,2N3616,2N3618
2N1136B	Ge-P	=2N1136:100V	23a$	-	AL102..103,AUY37,2N3616,2N3618
2N1137	Ge-P	NF/S-L,60V,6A,60W,B>75	23a$	USA	AL102..103,AUY28,2N3615..18,+
2N1137A	Ge-P	=2N1137:90V	23a$	-	AL102..103,AUY28,2N3616,2N3618
2N1137B	Ge-P	=2N1137:100V	23a$	-	AL102..103,AUY37,2N3616,2N3618
2N1138	Ge-P	NF/S-L,60V,6A,60W,B>100	23a$	USA	AL102..103,AUY28,2N3615..18,+
2N1138A	Ge-P	=2N1138:90V	23a$	-	AL102..103,AUY28,2N3616,2N3618
2N1138B	Ge-P	=2N1138:100V	23a$	-	AL102..103,AUY37,2N3616,2N3618
2N1139	Si-N	S,15V,0,1A,0,5W(Ta=100o),>100MHz	2a$	USA	BSV69,2N3724,2SC1072,2SC1385,+
2N114	Ge-P	HF,30V,Ueb=20V,0,2A,0,13W,20MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N1140	Si-N	S,40V,1W(Ta=100o),>35MHz	2a$	USA	BSV69,2N3724,2SC1072,2SC1385,+
2N1141(A)	Ge-P	VHF/UHF,35V,0,1A,0,3W,>1200MHz	2a$	Mot,Sem,Tix	(AFY18)
2N1142(A)	Ge-P	VHF/UHF,35V,0,1A,0,3W,>1000MHz	2a$	Mot,Sem,Tix	(AFY18)
2N1143(A)	Ge-P	VHF/UHF,35V,0,1A,0,3W,>800MHz	2a$	Mot,Sem,Tix	(AFY18)
2N1144	Ge-P	NF,16V,0,1A,0,14W,a=55	1a&	USA	AC125..126,AC151,2SB54,2SB56
2N1145	Ge-P	=2N1144:a=45	1a&	USA	AC125..126,AC151,2SB54,2SB56
2N1146	Ge-P	NF/S-L,40V,15A,90W	23a$	USA	2N1549..60
2N1146A	Ge-P	=2N1146:60V	23a$	-	2N1550..52,2N1554..56,2N1558..60
2N1146B	Ge-P	=2N1146:80V	23a$	-	2N1551..52,2N1555..56,2N1559..60
2N1146C	Ge-P	=2N1146:100V	23a$	-	2N1552,2N1556,2N1560
2N1147	Ge-P	NF/S-L,40V,15A,90W	23a$	USA	2N1549..60
2N1147A	Ge-P	=2N1147:60V	23a$	-	2N1550..52,2N1554..56,2N1558..60
2N1147B	Ge-P	=2N1147:80V	23a$	-	2N1551..52,2N1555..56,2N1559..60
2N1147C	Ge-P	=2N1147:100V	23a$	-	2N1552,2N1556,2N1560
2N1149	Si-N	Uni,45V,0,025A,0,15W,12MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N115	Ge-P	NF/S-L,32V,3A,50W,0,2MHz	-	Amp	-
2N1150	Si-N	Uni,45V,0,025A,0,15W,13MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1151	Si-N	Uni,45V,0,025A,0,15W,14MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1152	Si-N	Uni,45V,0,025A,0,15W,15MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1153	Si-N	Uni,45V,0,025A,0,15W,16MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1154	Si-N	Uni,50V,0,06A,0,75W,1MHz	?1a	USA	BC140..141,BC300..302,2N3053,+
2N1155	Si-N	=2N1154:80V,0,05A	?1a	USA	BC140..141,BC300..301,2N1889..90,+
2N1156	Si-N	=2N1154:120V,0,04A	?1a	USA	BC300,2N1883(A),2N2102,2N2405,+
2N1157	Ge-P	S-L,60V,40A,187W	?49a$	USA	-

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2N1157A	Ge-P	=2N1157:80V	?49a$	USA	-
2N1158(A)	Ge-P	HF,20V,0,1A,0,06..0,075W	2a	Csr,Etc	-
2N1159	Ge-P	NF/S-L,80V,5A,90W	23a$	USA	AL102..103,AUY22,2N3615..18,+
2N1116	Ge-P	-		Cbs	-
2N1160	Ge-P	=2N1159:7A	23a$	USA	AL102..103,AUY22,2N3615..18,+
2N1162(A)	Ge-P	NF/S-L,50V,25A,106W	23a$	USA,Mot	2N1651..53,2N2285..87
2N1163(A)	Ge-P	NF/S-L,50V,25A,106W	23a$	USA,Mot	2N1651..53,2N2285..87
2N1164(A)	Ge-P	NF/S-L,80V,25A,106W	23a$	USA,Mot	2N1652..53,2N2286..87
2N1165(A)	Ge-P	NF/S-L,80V,25A,106W	23a$	USA,Mot	2N1652..53,2N2286..87
2N1166(A)	Ge-P	NF/S-L,100V,25A,106W	23a$	USA,Mot	2N1653,2N2287
2N1167(A)	Ge-P	NF/S-L,100V,25A,106W	23a$	USA,Mot	2N1653,2N2287
2N1168	Ge-P	NF/S-L,50V,5A,45W	23a$	USA	AL102..103,AUY22,2N1545..48,+
2N1169	Ge-N	NF/S/Chopper,40V,0,4A,0,12W	2a	Csr,Sty	-
2N117	Si-N	NF/S,45V,25mA,0,15W,a>9,4MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1170	Ge-N	NF/S/Chopper,40V,0,4A,0,12W	2a	Csr,Sty	-
2N1171	Ge-P	NF/S,30V,0,4A,0,17W,>10MHz	2a	Mot	AC128,AC152..153,ASY26,ASY76..77
2N1172	Ge-P	NF/S,40V,1,5A(ss),5W	43a$	USA	(AD162)
2N1173	Ge-N	NF/S,35V,0,2A,0,25W	2a$	Wes	-
2N1174	Ge-P	NF/S,35V,0,2A,0,25W	2a$	Wes	-
2N1175(A)	Ge-P	NF/S,35V,0,5A,0,225W,4,2MHz	2a&	USA,Mot	AC128,AC152..153,ASY76..77
2N1176	Ge-P	NF,10V,0,3A,0,3W	2a	USA	AC128,AC152..153,2SB324,2SB415
2N1176A	Ge-P	=2N1176:40V	2a	-	ASY48,ASY76..77,2SB405ST
2N1176B	Ge-P	=2N1176:60V	2a	-	ASY48,ASY77
2N1177	Ge-P	HF,40V,10mA,0,08W,140MHz	1g	Cen,Rca,Sgs	AF106,AF109R,AF306
2N1178	Ge-P	HF,40V,10mA,0,08W,140MHz	1g	Cen,Rca,Sgs	AF106,AF109R,AF306
2N1179	Ge-P	HF,40V,10mA,0,08W,140MHz	1g	Cen,Rca,Sgs	AF106,AF109R,AF306
2N118(A)	Si-N	=2N117:a>19,5MHz,A:>8MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1180	Ge-P	HF,40V,10mA,0,08W,100MHz	1g	Cen,Rca,Sgs	AF106,AF109R,AF306
2N1182	Ge-P	NF/S-L,-/60V,5A,106W	23a$	Cen,Gpd	2N1541..43,2N1546..48;2N3615..18,+
2N1183	Ge-P	NF/S-L,45V,3A,7,5W,B>20	2a$	Gpd,Stc	AUY18
2N1183A	Ge-P	=2N1183:60V	2a$	-	AUY18
2N1183B	Ge-P	=2N1183:80V	2a$	-	-
2N1184	Ge-P	NF/S-L,45V,3A,7,5W,B>40	2a$	Gpd,Stc	AUY18
2N1184A	Ge-P	=2N1184:60V	2a$	-	AUY18
2N1184B	Ge-P	=2N1184:80V	2a$	-	-
2N1185	Ge-P	NF/S,45V,0,5A,0,2W,3MHz,a>190	2a	USA,Mot	ASY76..77
2N1186	Ge-P	NF/S,60V,0,5A,0,2W,1,5MHz,a>30	2a	USA,Mot	ASY77
2N1187	Ge-P	NF/S,60V,0,5A,0,2W,2MHz,a>50	2a	USA,Mot	ASY77
2N1188	Ge-P	NF/S,60V,0,5A,0,2W,2,5MHz,a>100	2a	USA,Mot	ASY77
2N1189	Ge-P	NF/S,45V,0,5A,0,2W,3,5MHz,a>75	2a	USA,Mot	ASY76..77,2SB405ST
2N119	Si-N	=2N117:a>38,6MHz	?1a	USA	BC167,BC182,BC237,BC547,+
2N1190	Ge-P	NF/S,45V,0,5A,0,2W,4,5MHz,a>125	2a	USA,Mot	ASY76..77,2SB405ST
2N1191	Ge-P	NF/S,40V,0,2A,0,2W,1,5MHz,a>30	2a	USA,Mot	ASY48,ASY76..77,2SB56A
2N1192	Ge-P	NF/S,40V,0,2A,0,2W,2MHz,a>50	2a	USA,Mot	ASY48,ASY76..77,2SB56A
2N1193	Ge-P	NF/S,40V,0,2A,0,2W,2,5MHz,a>100	2a	USA,Mot	ASY48,ASY76..77,2SB56A
2N1194	Ge-P	NF/S,40V,0,2A,0,2W,3MHz,a>190	2a	USA,Mot	ASY48,ASY76..77,2SB56A
2N1195	Ge-PNP	UHF,30V,0,04A,0,225W,>1200MHz	2a$	Mot,Spe	2N1141..43
2N1196	Si-PNP	GenP,70V,0,1A,0,35	2a	USA	BC212,BC256,BC266,BC556..
2N1197	Si-PNP	GenP,70V,0,1A,0,35	2a	USA	BC212,BC256,BC266,BC556..
2N1198	Ge-NPN	AF,Sw,25V,0,075A,0,065W,9MHz	?1a	USA	ASY28..29,ASY73..75
2N1199(A)	Si-NPN	HF/Sw,20V,0,1A,0,15W,125MHz	2a	Etc,Phc	BSV89..92,BSX92..93,2N2368..69(A),..
2N120	Si-NPN	=2N117:a>76,7MHz	?1a	USA	BC167,BC182,BC237,BC547..
2N1200	Si-NPN	HF,20V,0,1A,0,1W,4,3MHz	2a	Phc	BC168,BC183,BC238,BC548..
2N1201	Si-NPN	=2N1200:12MHz	2a	Phc	BC168,BC183,BC238,BC548..
2N1202	Ge-PNP	Sw,Pow,80V,3,5A,34W	?37b	USA	-
2N1203	Ge-PNP	=2N1202:120V	?37b	USA	-
2N1204(A)	Ge-PNP	Sw,20V,0,5A,0,3W,200MHz	2a$	USA,Mot	2N1495,2N2099..2100
2N1205	Si-NPN	GenP,20V,0,15W,>17MHz	2a	USA	BC168,BC183,BC238,BC548..
2N1206	Si-NPN	AF,Sw,60V,0,15A,3W(Tc=100°),>10MHz	2a	USA	BC140..141,BC300..302,2N3053..
2N1207	Si-NPN	=2N1206:125V	2a	USA	BC300,2N1893(A),2SC959,2SC2108..
2N1208(/I)	Si-NPN	Sw,Pow,60V,5A,45..80W	49a$	USA	2N3487..92
2N1209(/I)	Si-NPN	Sw,Pow,45V,5A,45..80W	49a$	USA	2N3487..92
2N1210(/I)	Si-NPN	Sw,Pow,60V,5A,45..80W	-	USA	2N1722..23
2N1211(/I)	Si-NPN	Sw,Pow,80V,5A,45..80W	-	USA	2N1722..23

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2N1212(/I)	Si-NPN	Sw,Pow,60V,5A,45..80W	49a$	USA	2N3487..92
2N1217	Ge-NPN	AF,Sw,20V,0,025A,0,075W,9MHz	?1a	Csr,Etc	-
2N1218	Ge-NPN	AF,Sw-Pow,45V,3A,20W	23a$	USA	-
2N1219	Si-PNP	GenP,30V,0,1A,0,25W,>5MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N122	Si-NPN	AF,Sw-Pow,120V,0,14A,9W,0,1MHz	-	Csr,Ssi	(BD424,MJE340,2SC2376,2SC2481,..)
2N1220	Si-PNP	GenP,30V,0,1A,0,25W,>2MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1221	Si-PNP	GenP,30V,0,1A,0,25W	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1222	Si-PNP	GenP,30V,0,1A,0,25W,>2MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1223	Si-PNP	GenP,40V,0,1A,0,25W,2MHz	2a	USA	(BC212,BC257,BC307,BC557,..)
2N1224	Ge-PNP	HF,40V,10mA,0,12W,30MHz	5g	USA	AF124..126,AF200
2N1225	Ge-PNP	HF,40V,10mA,0,12W,100MHz	5g	USA	AF124..125,AF200
2N1226	Ge-PNP	HF,60V,10mA,0,12W,30MHz	5g	USA	AF118
2N1227	Ge-PNP	AF,Sw-Pow,35V,3A,50W	23a$	USA	AD149,AUY19..20,2N2144..46..
2N1228	Si-PNP	GenP,15V,0,1A,0,4W,1,2MHz,B>14	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1229	Si-PNP	=2N1228:a>28	2a	USA	(BC213,BC258,BC308,BC558,..)
2N123	Ge-PNP	Sw,20V,0,125A,0,15W,8MHz,0,9/1μS	1a&	USA	ASY26..27,ASY48,ASY76..77
2N1230	Si-PNP	GenP,35V,0,1A,0,4W,1,2MHz,B>14	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1231	Si-PNP	=2N1230:a>28	2a	USA	(BC213,BC258,BC308,BC558,..)
2N1232	Si-PNP	GenP,60V,0,1A,0,4W,1MHz,a>14	2a	USA	(BC212,BC256,BC266,BC556,..)
2N1232A	Si-PNP	=2N1232:90V	2a	-	(2SC1890,2SC2240,2SC2459,2SC3245,..)
2N1233	Si-PNP	=2N1232:a>28	2a	USA	(BC212,BC256,BC266,BC556,..)
2N1234	Si-PNP	GenP,110V,0,1A,0,4W,0,8MHz,a>14	2a	USA	(2SC1890A,2SC2240,2SC2459,2SC3245,..)
2N1235	Si-NPN	Sw,Pow,120V,2A,85W	49a$	USA	2N3489,2N3492,2N5284..85
2N1238..1244	Si-PNP	=2N1228..1234:1W	Koax	Sem,Sty	→2N1228..1234
2N123A(/5)	Ge-PNP	=2N123:	2a	Syl	ASY26..27,ASY48,ASY76..77
2N124	Ge-NPN	Sw,10V,8mA,0,05W,3MHz	?1a	Csr,Etc	ASY26..27,ASY48,ASY76..77
2N1245	Ge-PNP	AF-Pow,30V,4A,20W	23a$	Cen	AD149,AUY28,2N1529..48,2SB449..
2N1246	Ge-PNP	AF-Pow,30V,4A,20W	23a$	Cen	AD149,AUY28,2N1529..48,2SB449..
2N1247	Si-NPN	GenP,6V,5mA,0,03W,5MHz,B>15	2a	USA	(BC168,BC183,BC238,BC548,..)
2N1248	Si-NPN	GenP,6V,5mA,0,03W,5MHz,B>15	2a	USA	(BC168,BC183,BC238,BC548,..)
2N1249	Si-NPN	GenP,6V,5mA,0,03W,5MHz,B>20	2a	USA	(BC168,BC183,BC238,BC548,..)
2N125	Ge-NPN	Sw,10V,8mA,0,05W,5MHz	?1a	Csr,Etc	ASY26..27,ASY48,ASY76..77
2N1250(/I)	Si-NPN	AF,Sw-Pow,60V,5A,75..85W	-	USA	2N1722..23,(BD245A,BD545A,BDV91..)
2N1251	Ge-NPN	AF,Sw,20V,0,1A,0,15W	?1a	USA	AC127,ASY28..29,ASY73..75
2N1252	Si-NPN	AF,Sw,30V,1A,0,6W,>40MHz,B>15	2a$	USA,Tix	BC140..141,BC300..302,2N2218..19,..
2N1252A	Si-NPN	=2N1252:60V	2a$	-	BC140..141,BC300..302,2N2218..19,..
2N1253	Si-NPN	AF,Sw,30V,1A,0,6W,>50MHz,B>30	2a$	USA,Tix	BC140..141,BC300..302,2N2218..19,..
2N1253A	Si-NPN	=2N1253:60V	2a$	-	BC140..141,BC300..302,2N2218..19,..
2N1254	Si-PNP	GenP,30V,0,1A,0,275W,<25/40nS	2a	USA	BC213,BC308,BC558,BSX36..
2N1255	Si-PNP	GenP,30V,0,1A,0,275W,<25/60nS	2a	USA	BC213,BC308,BC558,BSX36..
2N1256	Si-PNP	GenP,40V,0,1A,0,275W,<25/40nS	2a	USA	BC212,BC307,BC557,BSX36..
2N1257	Si-PNP	GenP,40V,0,1A,0,275W,<25/60nS	2a	USA	BC212,BC307,BC557,BSX36..
2N1258	Si-PNP	GenP,40V,0,1A,0,275W,<25/60nS	2a	USA	BC212,BC307,BC557,BSX36..
2N1259	Si-PNP	GenP,50V,0,1A,0,275W,<25/60nS	2a	USA	BC212,BC307,BC557,BSX36..
2N126	Ge-NPN	Sw,10V,8mA,0,05W,5MHz	?1a	Csr,Etc	ASY26..27,ASY48,ASY76..77
2N1260	Si-NPN	Sw,Pow,120V,2A,85W	-	USA	2N1722..23,(2SD731,2SD896)
2N1261(A)	Ge-PNP	Sw,Pow,80V,3,5A,34W,B>20	?37b	USA	-
2N1262(A)	Ge-PNP	=2N1261(A):B>30	?37b	USA	-
2N1263(A)	Ge-PNP	=2N1261(A):B>45	?37b	USA	-
2N1264	Ge-PNP	HF,20V,10mA,0,05W,3MHz	1g	Syl	AF124..127,AF200
2N1264/13	Ge-PNP	=2N1264:	?37b	-	-
2N1265	Ge-PNP	AF,20V,0,1A,0,1W	2a	USA	AC125..126,AC151,2SB54,2SB56
2N1265/5	Ge-PNP	=2N1265:10V,0,05W	2a	-	AC125..126,AC151,2SB54,2SB56
2N1266	Ge-PNP	AF,-/10V,0,08W	?1a	USA	AC125..126,AC151,2SB54,2SB56
2N1267	Si-NPN	GenP,20V,0,1A,0,15W,B>6	2a	Etc	BC168,BC183,BC238,BC548..
2N1268	Si-NPN	=2N1267:a>11	2a	Etc	BC168,BC183,BC238,BC548..
2N1269	Si-NPN	=2N1267:a>28	2a	Etc	BC168,BC183,BC238,BC548..
2N127	Ge-NPN	Sw,10V,8mA,0,05W,5MHz	?1a	TI	ASY26..27,ASY48,ASY76..77
2N1270	Si-NPN	=2N1267:	2a	Etc	BC168,BC183,BC238,BC548..
2N1271	Si-NPN	=2N1267:a>11	2a	Etc	BC168,BC183,BC238,BC548..
2N1272	Si-NPN	=2N1267:a>28	2a	Etc	BC168,BC183,BC238,BC548..
2N1273	Ge-PNP	AF,Sw,15V,0,2A,0,25W	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1274	Ge-PNP	=2N1273:25V	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1275	Si-PNP	Nix,100V,0,05A,0,25W	2a	USA	BF398,BSS68,BSV68,2SB715..716..

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2N1276	Si-NPN	GenP,40V,0,025A,0,15W,B>9	2a	USA,Tix	BC167,BC182,BC237,BCS47..
2N1277	Si-NPN	=2N1276:a>18	2a	USA,Tix	BC167,BC182,BC237,BCS47..
2N1278	Si-NPN	=2N1276:a>37	2a	USA,Tix	BC167,BC182,BC237,BCS47..
2N1279	Si-NPN	=2N1276:a>76	2a	USA,Tix	BC167,BC182,BC237,BCS47..
2N128	Ge-PNP	HF,10V,5mA,0,025W,>28MHz	37d	Spr,Ssi	AF124..127,AF200
2N1280	Ge-PNP	AF,Sw,16V,0,4A,0,2W,>5MHz,B>40	2a	USA	ASY76..77
2N1281	Ge-PNP	AF,Sw,16V,0,4A,0,2W,>7MHz,B>60	2a	USA	ASY76..77
2N1282	Ge-PNP	AF,Sw,16V,0,4A,0,2W,>10MHz,B>70	2a	USA	ASY76..77
2N1284	Ge-PNP	Sw,20V,0,4A,0,15W,8MHz	2a	USA	ASY76..77
2N1285	Ge-PNP	HF,40V,10mA,0,12W,100MHz	5g	Sty	AF124..125,AF200
2N1287(A)	Ge-PNP	AF,Sw,25V,0,3A,0,3W,1MHz	49a	Cen,Gpd	-
2N1288	Ge-NPN	Sw,15V,0,05A,0,075W,60MHz	2a	Gen,Sty	-
2N1289	Ge-NPN	=2N1288:20V	2a	Gen	-
2N129	Ge-PNP	HF,10V,5mA,0,03W,30MHz	37d	Spr	AF124..127,AF200
2N1291	Ge-PNP	AF,Sw-Pow,35V,3A,20W	23a$	USA	AD149,AUY19..20,2N2143..46..
2N1292	Ge-NPN	AF,Sw-Pow,35V,3A,25W	23a$	USA	2N1218
2N1293	Ge-PNP	=2N1291:60V	23a$	USA	AL102..103,AUY19..20,2N2144..46..
2N1294	Ge-NPN	=2N1292:60V	23a$	USA	-
2N1295	Ge-PNP	=2N1291:80V	23a$	USA	AL102..103,AUY20,2N2141,2N2146..
2N1296	Ge-NPN	=2N1292:80V	23a$	USA	-
2N1297	Ge-PNP	=2N1291:100V	23a$	USA	AL102..103,AUY34,2N2141,2N2146..
2N1298	Ge-NPN	=2N1292:100V	23a$	USA	-
2N1299	Ge-NPN	AF,Sw,40V,0,2A,0,15W,5MHz	2a&	USA	-
2N130	Ge-PNP	AF,25V,Ueb=12V,0,01A,85mW,0,7MHz	2a	USA	AC125..126,AC151,ASY26..27
2N1300	Ge-PNP	HF/Sw,13V,0,1A,0,15W,40MHz	2a	USA	-
2N1301	Ge-PNP	=2N1300:60MHz	2a	USA	-
2N1302	Ge-NPN	AF,Sw,25V,0,3A,0,15W,5MHz,B>20	2a&	USA,Phi,Tho	ASY28..29,ASY73..75
2N1303	Ge-PNP	AF,Sw,30V,0,3A,0,15W,5MHz,B>20	2a&	USA,Phi,Tho	ASY26,ASY76..77
2N1304	Ge-NPN	AF,Sw,25V,0,3A,0,15W,10MHz,B>40	2a&	USA,Phi,Tho	ASY28..29,ASY73..75
2N1305	Ge-PNP	AF,Sw,30V,0,3A,0,15W,10MHz,B>40	2a&	USA,Phi,Tho	ASY26,ASY76..77
2N1306	Ge-NPN	AF,Sw,25V,0,3A,0,15W,15MHz,B>60	2a&	USA,Phi,Tho	ASY28..29,ASY73..75
2N1307	Ge-PNP	AF,Sw,30V,0,3A,0,15W,15MHz,B>60	2a&	USA,Phi,Tho	ASY26,ASY76..77
2N1308	Ge-NPN	AF,Sw,25V,0,3A,0,15W,25MHz,B>80	2a&	USA,Phi,Tho	ASY28..29,ASY73..75
2N1309(A)	Ge-PNP	AF,Sw,30V,0,3A,0,15W,20MHz,B>80	2a&	USA,Phi,Tho	ASY26,ASY76..77
2N130A	Ge-PNP	AF,45V,Ueb=12V,0,1A,0,1W	?40e	-	ASY48,ASY76..77
2N131	Ge-PNP	AF,25V,Ueb=12V,0,01A,85mW,0,8MHz	2a	USA	AC125..126,AC151,ASY26..27
2N1310	Ge-NPN	Nix,90V,0,12W	2a	USA	-
2N1311	Ge-NPN	Nix,75V,0,12W	2a	USA	-
2N1312	Ge-NPN	Nix,50V,0,12W	2a	USA	-
2N1313	Ge-PNP	AF,Sw,30V,0,4A,0,18W,12MHz	2a	USA	ASY76..77
2N1314	Ge-PNP	AF,Sw-Pow,40V,3,5A,12W(Tc=70°)	23a$	USA	AD149,AUY19..20,2N2143..46..
2N1315	Ge-PNP	AF,Sw-Pow,32V,3,5A,12W(Tc=70°)	23a$	USA	AD149,AUY19..20,2N2137..46..
2N1316	Ge-PNP	AF,Sw,30V,0,4A,0,2W,>10MHz	2a	USA	ASY76..77
2N1317	Ge-PNP	AF,Sw,20V,0,4A,0,2W,>10MHz	2a	USA	ASY76..77
2N1318	Ge-PNP	AF,Sw,10V,0,4A,0,2W,>10MHz	2a	USA	ASY76..77
2N1319	Ge-PNP	AF,Sw,20V,0,4A,0,2W,6MHz	2a	USA	ASY76..77
2N131A	Ge-PNP	AF,45V,Ueb=12V,0,1A,0,1W	?40e	-	ASY48,ASY76..77
2N132	Ge-PNP	AF,25V,Ueb=12V,0,01A,85mW,1MHz	2a	USA	AC125..126,AC151,ASY26..27
2N1320	Ge-PNP	AF,Sw-Pow,35V,3A,20W	?37b$	Gpd,Stc	-
2N1321	Ge-NPN	AF,Sw-Pow,35V,3A,25W	?37b$	Gpd,Stc	-
2N1322	Ge-PNP	=2N1320:60V	?37b$	Gpd,Stc	-
2N1323	Ge-NPN	=2N1321:60V	?37b$	Gpd,Stc	-
2N1324	Ge-PNP	=2N1320:80V	?37b$	Gpd,Stc	-
2N1325	Ge-NPN	=2N1321:80V	?37b$	Gpd,Stc	-
2N1326	Ge-PNP	=2N1320:100V	?37b$	Gpd,Stc	-
2N1327	Ge-NPN	=2N1321:100V	?37b$	Gpd,Stc	-
2N1328	Ge-PNP	=2N1320:	?37b$	Gpd,Stc	-
2N1329	Ge-NPN	=2N1321:	?37b$	Gdp,Stc	-
2N132A	Ge-PNP	AF,35V,Ueb=12V,0,1A,0,1W	?40e	-	ASY48,ASY76..77
2N133	Ge-PNP	AF,25V,Ueb=12V,0,01A,85mW	2a	USA	AC125..126,AC151,ASY26..27
2N1330	Ge-NPN	=2N1321:60V	?37b$	Gpd,Stc	-
2N1331	Ge-PNP	=2N1320:80V	?37b$	Gpd,Stc	-
2N1332	Ge-NPN	=2N1321:80V	?37b$	Gpd,Stc	-
2N1333	Ge-PNP	=2N1320:100V	?37b$	Gpd,Stc	-

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2N1334	Ge-NPN	=2N1321: 100V	?37b$	Gpd,Stc	-
2N1335	Si-NPN	HF-Dr, 120V,0,3A,Pq>0,25W(70MHz)	2a$	USA	-
2N1336	Si-NPN	HF-Dr, 120V,0,3A,Pq>0,5W(70MHz)	2a$	USA	-
2N1337	Si-NPN	HF-Dr, 120V,0,3A,Pq>0,7W(70MHz)	2a$	USA	-
2N1338	Si-NPN	HF-Dr, 80V,0,3A,Pq>0,5W(70MHz)	2a$	USA	-
2N1339	Si-NPN	HF-Dr, 120V,0,3A,Pq>0,25W(70MHz)	2a$	USA	-
2N133A	Ge-PNP	AF, 35V, Ueb=12V,0,1A,0,1W	?40e	-	ASY48,ASY76..77
2N1340	Si-NPN	HF-Dr, 150V,0,3A,Pq>0,5W(70MHz)	2a$	USA	-
2N1341	Si-NPN	HF-Dr, 120V,0,3A,Pq>0,75W(70MHz)	2a$	USA	-
2N1342	Si-NPN	HF-Dr, 150V,0,3A,Pq>1W(70MHz)	2a$	USA	-
2N1343	Ge-PNP	AF,Sw, 20V,0,4A,0,15W,6MHz	2a	USA	ASY76..77
2N1344	Ge-PNP	AF,Sw, 15V,0,4A,0,15W,>7MHz	2a	USA	ASY76..77
2N1345	Ge-PNP	AF,Sw, 10V,0,4A,0,15W,>10MHz	2a	USA	ASY76..77
2N1346	Ge-PNP	AF,Sw, 12V,0,4A,0,15W,>10MHz	2a	USA	ASY76..77
2N1347	Ge-PNP	AF,Sw, 20V,0,2A,0,15W,>5MHz	2a	USA	ASY26..27,ASY76..77
2N1348	Ge-PNP	AF,Sw, 40V,0,4A,0,2W,5MHz	2a	USA	ASY76..77
2N1349	Ge-PNP	AF,Sw, 40V,0,4A,0,2W,10MHz	2a	USA	ASY76..77
2N135	Ge-PNP	HF, 20V,0,05A,0,1W,4,5MHz	1a&	Csr,Etc	AF124..127,AF200,2N3323..25
2N1350	Ge-PNP	AF,Sw, 50V,0,4A,0,2W,8MHz	2a	USA	ASY76..77
2N1351	Ge-PNP	AF,Sw, 40V,0,4A,0,2W,8MHz	2a	USA	ASY76..77
2N1352	Ge-PNP	AF,Sw, 30V,0,2A,0,15W,>2,5MHz	2a	USA	ASY26..27,ASY76..77
2N1353	Ge-PNP	AF,Sw, 15V,0,2A,0,2W,3,5MHz	2a	USA	ASY26..27,ASY76..77
2N1354	Ge-PNP	AF,Sw, 30V,0,2A,0,2W,4,5MHz	2a	USA	ASY26..27,ASY76..77
2N1355	Ge-PNP	AF,Sw, 30V,0,2A,0,2W,8MHz	2a	USA	ASY26..27,ASY76..77
2N1356	Ge-PNP	AF,Sw, 30V,0,2A,0,2W,>5MHz	2a	USA	ASY26..27,ASY76..77
2N1357	Ge-PNP	AF,Sw, 30V,0,2A,0,2W,12MHz	2a	USA	ASY26..27,ASY76..77
2N1358(A,M)	Ge-PNP	AF,Sw-Pow, 80V,15A,150W	38a$	USA,Mot	2N1982,2N2075,2N2079,2N2492..93
2N1359	Ge-PNP	AF,Sw-Pow, 50V,3A,106W,B>35	23a$	USA,Mot	2N1540..43,2N1546..48,2N3615..18
2N136	Ge-PNP	HF, 20V,0,05A,0,1W,6,5MHz	1a&	Csr,Etc	AF124..127,AF200,2N3323..25
2N1360	Ge-PNP	=2N1359: B>60	23a$	USA,Mot	2N1540..43,2N1546..48,2N3615..18
2N1361(A)	Ge-PNP	AF,Sw, 25V,0,2A,0,15..0,2W,4MHz	2a&	Cen,Gen	ASY26..27,ASY76..77
2N1362	Ge-PNP	AF,Sw-Pow, 100V,3A,106W,B>35	23a$	USA,Mot	2N1542..43,2N1547..48,2N3616,2N3618
2N1363	Ge-PNP	=2N1362: B>60	23a$	USA,Mot	2N1542..43,2N1547..48,2N3616,2N3618
2N1364	Ge-PNP	=2N1362: 120V	23a$	USA,Mot	2N1543,2N1548,2N2290,2N2293
2N1365	Ge-PNP	=2N1362: 120V,B>60	23a$	USA,Mot	2N1543,2N1548,2N2290,2N2293
2N1366	Ge-NPN	AF,Sw, 18V,0,025A,0,1W,>5MHz	2a	USA	-
2N1367	Ge-NPN	=2N1366: >2,5MHz	2a	USA	-
2N137	Ge-PNP	HF, 20V,0,05A,0,1W,10MHz	1a&	Csr,Etc	AF124..127,AF200,2N3323..25
2N1370	Ge-PNP	AF,Sw, 25V,0,2A,0,25W,B>45	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1371	Ge-PNP	=2N1370: 45V	2a	USA,Tix	2SB56A
2N1372	Ge-PNP	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1373	Ge-PNP	=2N1370: 45V	2a	USA,Tix	2SB56A
2N1374	Ge-PNP	=2N1370: B>50	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1375	Ge-PNP	=2N1370: 45V,B>50	2a	USA,Tix	2SB56A
2N1376	Ge-PNP	=2N1370: B>75	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1377	Ge-PNP	=2N1370: 45V,B>75	2a	USA,Tix	2SB56A
2N1378	Ge-PNP	=2N1370: 12V,B>95	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1379	Ge-PNP	=2N1370: B>95	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N138	Ge-PNP	AF,Sw, 20V,0,15A,0,15W,1,2MHz	?1a	Etc	AC125..126,AC151,ASY26..27
2N1380	Ge-PNP	=2N1370: 12V,B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1381	Ge-PNP	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1382	Ge-PNP	=2N1370: B>50	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1383	Ge-PNP	=2N1370: B>30	2a	USA,Tix	AC125..126,AC151,2SB54,2SB56
2N1384	Ge-PNP	AF,Sw, 30V,0,5A,0,24W,35MHz	2a$	Rca	-
2N1385	Ge-PNP	HF/Sw, 25V,0,1A,0,75W,>250MHz	2a$	TI	-
2N1386	Si-NPN	GenP, 25V,0,05A,0,3W,60MHz	2a	USA	BC238,BC548,BSV59,2N2221..22(A),..
2N1387	Si-NPN	GenP, 30V,0,05A,0,3W,50MHz	2a	USA	BC238,BC548,BSV59,2N2221..22(A),..
2N1388	Si-NPN	GenP, 45V,0,05A,0,3W,>50MHz	2a	USA	BC237,BC547,BSV59,2N2221..22(A),..
2N1389	Si-NPN	GenP, 50V,0,05A,0,3W,>25MHz	2a	USA	BC237,BC547,BSV59,2N2221..22(A),..
2N138A,B	Ge-PNP	=2N138: 45V,0,13W,B:0,1A	?40e	Ray	ASY48,ASY76..77
2N139	Ge-PNP	HF, 16V,15mA,0,035W,4,7MHz	1a	Csr,Etc	AF124..127,AF200,2N3323..25
2N1390	Si-NPN	GenP, 20V,0,05A,0,3W,>20MHz	2a	USA	BC238,BC548,BSV59,2N2221..22(A),..
2N1391	Ge-NPN	AF,Sw, 25V,0,15W,>3MHz	2a	USA	AC127,ASY28..29,ASY73..75
2N1392	Opto	-	-	-	-

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2N1393	Opto	-	-		-
2N1394	Opto	-	-		-
2N1395	Ge-PNP	HF,40V,10mA,0,12W,30MHz	5g	USA	AF124..126,AF200
2N1396	Ge-PNP	=2N1395:100MHz	5g	USA	AF106,AF109R,AF306
2N1397	Ge-PNP	=2N1395:120MHz	5g	USA	AF106,AF109R,AF306
2N1398	Ge-PNP	HF,-/20V,10mA,0,035W,>140MHz	5g	TI	AF106,AF109R,AF306
2N1399	Ge-PNP	HF,-/20V,10mA,0,035W,>140MHz	5g	TI	AF106,AF109R,AF306
2N140	Ge-PNP	HF,16V,15mA,0,035W,7MHz	1a	Etc	AF124..127,AF200,2N3323..25
2N1400	Ge-PNP	HF,-/20V,10mA,0,035W,>100MHz	5g	TI	AF106,AF109R,AF306
2N1401(A)	Ge-PNP	HF,-/20V,10mA,0,035W,>120MHz	5g	TI	AF106,AF109R,AF306
2N1402	Ge-PNP	HF,-/20V,10mA,0,035W,>100MHz	5g	TI	AF106,AF109R,AF306
2N1403	Ge-PNP	HF,15V,0,1A,0,25W,>200MHz	2a$	TI	(AF109R,AF139,AF239(S))
2N1404(A)	Ge-PNP	AF,Sw,25V,0,3A,0,15W,>4MHz	2a$	USA,Tix	ASY76..77
2N1405	Ge-PNP	HF,30V,0,05A,0,075W,1100MHz	5g	TI	AF139,AF239(S)
2N1406	Ge-PNP	HF,30V,0,05A,0,075W,1100MHz	5g	TI	AF139,AF239(S)
2N1407	Ge-PNP	HF,30V,0,05A,0,075W,1100MHz	5g	TI	AF139,AF239(S)
2N1408	Ge-PNP	AF,Sw,50V,0,2A,0,15W	2a	USA,Mot	ASY48,ASY77
2N1409(A)	Si-NPN	AF,Sw,30V,0,5A,0,6..0,8W,B>15	2a$	USA	BC140..141,BC300..302,2N2218..19..
2N141(/13)	Ge-PNP	AF-Dr/Out,60V,Ueb=30V,0,8A,0,4MHz	-	USA	-
2N1410(A)	Si-NPN	=2N1409(A):B>30	2a$	USA	BC140..141,BC300..302,2N2218..19..
2N1411	Ge-PNP	Sw,-/50V,0,025W,70MHz	37d	USA	-
2N1412(A)	Ge-PNP	AF,Sw-Pow,100V,15A,150W	38a$	USA,Mot	2N2493
2N1413	Ge-PNP	AF,Sw,35V,0,5A,0,225W,B>25	2a&	USA,Mot	AC128,AC152..153,2SB324,2SB415
2N1414	Ge-PNP	=2N1413:B>34	2a&	USA,Mot	AC128,AC152..153,2SB324,2SB415
2N1415	Ge-PNP	=2N1413:B>53	2a&	USA,Mot	AC128,AC152..153,2SB324,2SB415
2N1416	Ge-PNP	=2x2N223:gep.	2x37e	Csr,Etc	→2N223
2N1417	Si-NPN	HF/Sw/Chopper,15V,0,05A,0,15W	2a	USA	(BC168,BC183,BC238,BC548,..)
2N1418	Si-NPN	=2N1417:30V	2a	USA,TO-5	(BC168,BC183,BC238,BC548,..)
2N1419	Ge-PNP	AF,Sw-Pow,80V,25A,87W	23a$	Cen	2N1652..53,2N2286..87
2N142(/13)	Ge-NPN	AF-Dr/Out,60V,Ueb=30V,0,8A,0,4MHz	-	USA	-
2N1420(A)	Si-NPN	AF,Sw,60V,1A,0,6..0,8W,>50MHz	2a$	USA,EUR	BC140..141,BC300..302,2N1990..
2N1421	Si-NPN	Sw,Pow,60V,3A,30W	49a$	Tra	2N5002,2N5004,2N5284..85
2N1422	Si-NPN	Sw,Pow,60V,3A,30W	23a$	Tra	AL102..103,AUY19..20,2N2144..46..
2N1423	Si-NPN	Sw,Pow,60V,3A,60W	23a$	Tra	AL102..103,AUY19..20,2N2144..46..
2N1424	Si-NPN	Sw,Pow,60V,3A,60W	49a$	Tra	2N5002,2N5004,2N5284..85
2N1425	Ge-PNP	HF,24V,10mA,0,08W,>6MHz	1g	Rca	AF124..127,AF200
2N1426	Ge-PNP	HF,24V,10mA,0,08W,>6MHz	1g	Rca	AF124..127,AF200
2N1427	Ge-PNP	HF/Sw,6V,0,05A,0,025W,60MHz	37d	USA	ASZ21,2N705,2N960..967
2N1428	Si-PNP	AF,Sw,6V,0,05A,0,1W,>18MHz	2a	USA	BC213,BC258,BC308,BC558..
2N1429	Si-PNP	=2N1428	2a	USA	BC213,BC258,BC308,BC558..
2N143(/13)	Ge-PNP	AF-Dr/Out,60V,Ueb=30V,0,8A,0,4MHz	-	USA	-
2N1430	Ge-PNP	Sw,Pow,100V,10A,70W	23a$	Gpd,Idi	AL100..101,AUY37,2N2290,2N2293
2N1431	Ge-NPN	AF,Sw,20V,0,1A,0,18W	?1a	Etc	AC127,AC176,AC187
2N1432	Ge-PNP	HF,45V,10mA,0,1W	5g	Syl	AF124..127,AF200
2N1433	Ge-PNP	AF,Sw-Pow,80V,3,5A,12W(Tc=75°),B>20	?37b$	Cbs	-
2N1434	Ge-PNP	=2N1433:B>45	?37b$	Cbs	-
2N1435	Ge-PNP	=2N1433:B>30	?37b$	Cbs	-
2N1436	Ge-PNP	Sw,15V,0,05A,0,05W,<70/-nS	2a$	Phc	ASZ21,2N705,2N960..67
2N1437	Ge-PNP	Sw,Pow,100V,3A,23W	?37b$	Gpd,Stc	-
2N1438	Ge-PNP	Sw,Pow,100V,3A,23W	?37b$	Gpd,Stc	-
2N1439	Si-PNP	GenP,50V,0,1A,0,4W,>1MHz,B=9	2a	USA	BC212,BC257,BC307,BC557..
2N144(/13)	Ge-NPN	AF-Dr/Out,60V,Ueb=30V,0,8A,0,4MHz	-	USA	-
2N1440	Si-PNP	=2N1439:60V,a=16	2a	USA	BC212,BC256,BC266,BC556..
2N1441	Si-PNP	=2N1439:a=27	2a	USA	BC212,BC257,BC307,BC557..
2N1442	Si-PNP	=2N1439:a=43	2a	USA	BC212,BC257,BC307,BC557..
2N1443	Si-PNP	=2N1439:a=65	2a	USA	BC212,BC257,BC307,BC557..
2N1444	Si-NPN	AF,Sw,60V,0,25A,0,5W,<250/250nS	2a$	Wes	BC140..141,BC300..302,2N2218..19..
2N1445	Si-NPN	AF,Sw,120V,0,75A,0,8W	2a$	USA	BC300,2N1893,2SC959,2SC2108..
2N1446	Ge-PNP	AF,Sw,45V,0,4A,0,2,B=30	2a	USA	2N1189..90,2SB405ST
2N1447	Ge-PNP	=2N1446:a=45	2a	USA	2N1189..90,2SB405ST
2N1448	Ge-PNP	=2N1446:a=65	2a	USA	2N1189..90,2SB405ST
2N1449	Ge-PNP	=2N1446:a=80	2a	USA	2N1189..90,2SB405ST
2N145	Ge-NPN	HF,20V,5mA,0,065W,B=30,>0,6MHz	?1a	Csr,Etc	-
2N1450	Ge-PNP	Sw,30V,0,1A,0,12W,<200/170nS	2a	USA	2N2955..57

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2N1451	Ge-PNP	AF,45V,0,4A,0,2W,B>20	2a	USA	2N1189..90,2SB405ST
2N1452	Ge-PNP	=2N1451:B>30	2a	USA	2N1189..90,2SB405ST
2N1453	Ge-PNP	AF,Sw-Pow,30V,5A,43W,B>40	?37b$	Cbs	-
2N1454	Ge-PNP	=2N1453:B>70	?37b$	Cbs	-
2N1455	Ge-PNP	=2N1453:60V	?37b$	Cbs	-
2N1456	Ge-PNP	=2N1453:60V,B>70	?37b$	Cbs	-
2N1457	Ge-PNP	=2N1453:80V	?37b$	Cbs	-
2N1458	Ge-PNP	=2N1453:80V,B>70	?37b$	Cbs	-
2N146	Ge-NPN	=2N145:a=50,>0,7MHz	?1a	Etc	-
2N1461	Ge-PNP	=2N1453:	?37b$	Cbs	-
2N1462	Ge-PNP	=2N1453:B>70	?37b$	Cbs	-
2N1463	Ge-PNP	=2N1453:60V	?37b$	Cbs	-
2N1464	Ge-PNP	=2N1453:60V,B>70	?37b$	Cbs	-
2N1465	Ge-PNP	AF,Sw-Pow,120V,3A,20W	?37b$	USA	-
2N1466	Ge-PNP	=2N1465	?37b$	USA	-
2N1468	Si-NPN	Avalanche-Sw	2a	Ray	-
2N1469	Si-PNP	GenP,40V,0,1A,0,25W,>2MHz	2a	USA	BC212,BC257,BC307,BCS57..
2N147	Ge-NPN	=2N145:a=70,>0,8MHz	?1a	Etc	-
2N1470	Si-NPN	AF,Sw-Pow,60V,3A,55W	23a$	Csr,Idi	BD245A,BDV91,BDX91,2N4914..15..
2N1471	Ge-PNP	Sw,12V,0,2A,0,2W,>3MHz	2a	USA	2N705(A),2N960..967,2N2955..57
2N1472	Si-NPN	Sw,25V,0,1A,0,15W,140MHz	2a	USA	BSW41,BSY62..63,2N706A,2N708..
2N1473	Ge-NPN	AF,Sw,40V,0,4A,0,25W,8MHz	2a&	USA	-
2N1474(A)	Si-PNP	Sym,60/60/60V,0,1A,0,25W	2a	USA	-
2N1475	Si-PNP	Sym,60/60/60V,0,1A,0,25W	2a	USA	-
2N1476	Si-PNP	Sym,100/100/100V,0,1A,0,25W	2a	USA	-
2N1477	Si-PNP	Sym,100/100/100V,0,1A,0,25W	2a	USA	-
2N1478	Ge-PNP	HF/Sw,30V,0,5A,0,25W,8MHz	2a$	USA	ASY76..77
2N1479	Si-NPN	AF,Sw,60V,1,5A,5W(Tc=25°),B>20	2a$	USA,Rca	BCX40,BSS15..16,2N5320..21..
2N148	Ge-NPN	HF,16V,5mA,0,065W,B=35,>0,5MHz	?1a	TI	-
2N1480	Si-NPN	=2N1479:100V	2a$	USA,Rca	BCX40,BSS15,BSV84,2N5320..
2N1481	Si-NPN	=2N1479:B>35	2a$	USA,Rca	BCX40,BSS15..16,2N5320..21..
2N1482	Si-NPN	=2N1479:100V,B>35	2a$	USA,Rca	BCX40,BSS15,BSV84,2N5320..
2N1483	Si-NPN	AF,Sw-Pow,60V,3A,25W(Tc=25°),B>20	2a$	USA,Rca	(BD241A,BD535,BD539A,BD935,..)
2N1484	Si-NPN	=2N1483:100V	2a$	USA,Rca	(BD241C,BD539C,BD937,2SD712,..)
2N1485	Si-NPN	=2N1483:B>35	2a$	USA,Rca	(BD241A,BD535,BD539A,BD935,..)
2N1486	Si-NPN	=2N1483:100V,B>35	2a$	USA,Rca	(BD241C,BD539C,BD937,2SD712,..)
2N1487	Si-NPN	AF,Sw-Pow,60V,6A,75W,B>15	23a$	USA,Rca,Tix	BD245A,BDV91,BDX91,2N4914..15..
2N1488	Si-NPN	=2N1487:100V	23a$	USA,Rca,Tix	BD245C,BDV95,BDX95,2N5758..60..
2N1489	Si-NPN	=2N1487:B>25	23a$	USA,Rca,Tix	BD245A,BDV91,BDX91,2N4914..15..
2N148A	Ge-NPN	=2N148:32V	?1a	-	-
2N149	Ge-NPN	HF,16V,5mA,0,065W,B=38,>0,5MHz	?1a	TI	-
2N1490	Si-NPN	=2N1487:100V,B>25	23a$	USA,Rca,Tix	BD245C,BDV95,BDX95,2N5758..60..
2N1491	Si-NPN	VHF,30V,0,1A,0,5W,250MHz	2a$	USA,Rca	BFW16..17
2N1492	Si-NPN	VHF,60V,0,1A,0,5W,275MHz	2a$	USA,Rca	-
2N1493	Si-NPN	VHF,100V,0,1A,0,5W,300MHz	2a$	USA,Rca	-
2N1494(A)	Ge-PNP	Sw,20V,0,5A,0,75W,>110MHz	49a$	Mot,Sty	2N2096
2N1495(A)	Ge-PNP	Sw,40V,0,5A,0,3W,>150MHz	2a$	Mot,Sty	2N2100
2N1496	Ge-PNP	=2N1495:0,5W	49a$	Mot,Sty	2N2097
2N1499(A)	Ge-PNP	Sw,20V,0,1A,0,06W,>100MHz	2a	USA	2N2955..57
2N1499B	Ge-PNP	Sw,30V,0,1A,0,075W,>150MHz	2a	-	2N2955..57
2N149A	Ge-NPN	=2N149:32V	?1a	-	-
2N150	Ge-NPN	HF,16V,5mA,0,065W,B=41,>0,5MHz	?1a	TI	-
2N1500(/18)	Ge-PNP	Sw,30V,0,1A,0,075W,>150MHz	2a	USA	ASZ21,2N705,2N960..67,2N2955..57
2N1501	Ge-PNP	Sw,Pow,60V,3,5A,34W	?37b	USA	-
2N1502	Ge-PNP	=2N1501:40V	?37b	USA	-
2N1504(/10)	Ge-PNP	Sw,Pow,80V,3A,23W	?37b$	Gpd,Stc	-
2N1505	Si-NPN	HF-Osc/Dr,50V,0,5A,Pq=1,1W(70MHz)	2a$	USA	BFX55
2N1506	Si-NPN	HF-Osc/Dr,60V,0,5A,Pq=1,3W(70MHz)	2a$	USA	BFX55
2N1506A	Si-NPN	=2N1506:80V	2a$	-	(BFX55)
2N1507	Si-NPN	AF,Sw,60V,1A,0,6W,>50MHz	2a$	USA,Tix	BC140..141,BC300..302,2N1990..
2N1508	Si-NPN	=2N1509:100V	2a$	Sty	BC141,BC300,BSW39,2N1990..
2N1509	Si-NPN	AF,Sw,60V,1A,1W	2a$	Sty	BC140..141,BC300..302,2N2218..19..
2N150A	Ge-NPN	=2N150:32V	?1a	-	-
2N151	Ge-PNP	-		old	-

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2N1510	Ge-NPN	AF,Sw,75V,0,02A,0,075W	?1a	USA	-
2N1511	Si-NPN	Sw,Pow,60V,6A,75W,B>15	38a$	USA	(BD245A,BDV91,BDX91,2N4914..15,..)
2N1512	Si-NPN	=2N1511:100V	38a$	USA	(BD245C,BDV95,BDX95,2N5758..60,..)
2N1513	Si-NPN	=2N1511:B>25	38a$	USA	(BD245A,BDV91,BDX91,2N4914..15,..)
2N1514	Si-NPN	=2N1511:100V,B>25	38a$	USA	(BD245C,BDV95,BDX95,2N5758..60,..)
2N1515	Ge-PNP	HF,20V,10mA,0,083W,70MHz	1g	Amp	AF124..126,AF200
2N1516	Ge-PNP	HF,25V,10mA,0,083W,70MHz	1g	Amp	AF124..126,AF200
2N1517	Ge-PNP	HF,20V,10mA,0,083W,70MHz	1g	Amp	AF124..126,AF200
2N1517A	Ge-PNP	=2N1517:40V,0,1W	1g	-	AF124..126,AF200
2N1518	Ge-PNP	AF,Sw-Pow,50V,25A,87,5W	38a$	USA	2N2153..55,2N2157..59
2N1519	Ge-PNP	=2N1518:80V	38a$	USA	2N2155,2N2159
2N152	Ge-PNP	-		old	-
2N1520	Ge-PNP	AF,Sw-Pow,50V,35A,87,5W	38a$	USA	2N2153..55,2N2157..59
2N1521	Ge-PNP	=2N1520:80V	38a$	USA	2N2155,2N2159
2N1522	Ge-PNP	AF,Sw-Pow,50V,50A,87,5W	38a$	USA	2N4049..50,2N4052..53
2N1523	Ge-PNP	=2N1522:80V	38a$	USA	2N4050,2N4053
2N1524	Ge-PNP	HF,24V,10mA,0,08W,33MHz	2a	USA	AF124..127,AF200
2N1524/33	Ge-PNP	=2N1524:0,12W	5g	-	AF124..127,AF200
2N1525	Ge-PNP	HF,24V,10mA,0,08W,33MHz	1a	USA	AF124..127,AF200
2N1526	Ge-PNP	HF,24V,10mA,0,08W,33MHz	2a	USA	AF124..127,AF200
2N1526/33	Ge-PNP	=2N1526:0,12W	5g	-	AF124..127,AF200
2N1527	Ge-PNP	HF,24V,10mA,0,08W,33MHz	1a	USA	AF124..127,AF200
2N1528	Si-NPN	HF/Sw,25V,0,02A,0,15W,20MHz	2a	Ray	BC168,BC183,BC238,BC548..
2N1529(A)	Ge-PNP	AF,Sw-Pow,40V,5A,106W,B>20	23a$	USA,Mot,Tix	2N3611..18
2N153	Ge-PNP	-		old	-
2N1530(A)	Ge-PNP	=2N1529:60V	23a$	USA,Mot,Tix	2N3612,2N3614,2N3615..18
2N1531(A)	Ge-PNP	=2N1529:80V	23a$	USA,Mot,Tix	2N3615..18
2N1532(A)	Ge-PNP	=2N1529:100V	23a$	USA,Mot,Tix	2N3616,2N3618
2N1533(A)	Ge-PNP	=2N1529:120V	23a$	USA,Mot,Tix	-
2N1534(A)	Ge-PNP	AF,Sw-Pow,40V,5A,106W,B>35	23a$	USA,Mot,Tix	2N3611..18
2N1535(A)	Ge-PNP	=2N1534:60V	23a$	USA,Mot,Tix	2N3612,2N3614,2N3615..18
2N1536(A)	Ge-PNP	=2N1534:80V	23a$	USA,Mot,Tix	2N3615..18
2N1537(A)	Ge-PNP	=2N1534:100V	23a$	USA,Mot,Tix	2N3616,2N3618
2N1538(A)	Ge-PNP	=2N1534:120V	23a$	USA,Mot,Tix	-
2N1539(A)	Ge-PNP	AF,Sw-Pow,40V,5A,106W,B>50	23a$	USA,Mot,Tix	2N3611..18
2N154	Ge-PNP	-		old	-
2N1540(A)	Ge-PNP	=2N1539:60V	23a$	USA,Mot,Tix	2N3612,2N3614,2N3615..18
2N1541(A)	Ge-PNP	=2N1539:80V	23a$	USA,Mot,Tix	2N3615..18
2N1542(A)	Ge-PNP	=2N1539:100V	23a$	USA,Mot,Tix	2N3616,2N3618
2N1543(A)	Ge-PNP	=2N1539:120V	23a$	USA,Mot,Tix	-
2N1544(A)	Ge-PNP	AF,Sw-Pow,40V,5A,106W,B>75	23a$	USA,Mot,Tix	(2N3611..18)
2N1545(A)	Ge-PNP	=2N1544:60V	23a$	USA,Mot,Tix	(2N3612,2N3614,2N3615..18)
2N1546(A)	Ge-PNP	=2N1544:80V	23a$	USA,Mot,Tix	(2N3615..18)
2N1547(A)	Ge-PNP	=2N1544:100V	23a$	USA,Mot,Tix	(2N3616,2N3618)
2N1548(A)	Ge-PNP	=2N1544:120V	23a$	USA,Mot,Tix	-
2N1549(A)	Ge-PNP	AF,Sw-Pow,40V,15A,106W,B>10	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N155	Ge-PNP	AF,Sw-Pow,30V,Ueb=15V,3A,20W,0,18MHz	23a$	USA	AD149,AUY19..20,2N2137,2N2142..
2N1550(A)	Ge-PNP	=2N1549:60V	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N1551(A)	Ge-PNP	=2N1549:80V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N1552(A)	Ge-PNP	=2N1549:100V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N1553(A)	Ge-PNP	AF,Sw-Pow,40V,15A,106W,B>30	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N1554(A)	Ge-PNP	=2N1553:60V	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N1555(A)	Ge-PNP	=2N1553:80V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N1556(A)	Ge-PNP	=2N1553:100V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N1557(A)	Ge-PNP	AF,Sw-Pow,40V,15A,106W,B>50	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N1558(A)	Ge-PNP	=2N1557:60V	23a$	USA,Mot,Tix	2N1651..53,2N2285..87
2N1559(A)	Ge-PNP	=2N1557:80V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N156	Ge-PNP	=2N155:25W	-	USA	(AD149,AUY19..20,2N2137,2N2142,..)
2N1560(A)	Ge-PNP	=2N1557:100V	23a$	USA,Mot,Tix	2N1652..53,2N2286..87
2N1561	Ge-PNP	VHF-A/Dr,25V,0,25A,Pq>0,5W(160MHz)	?2a	Mot	(2N1692)
2N1562	Ge-PNP	VHF-A/Dr,25V,0,25A,Pq>0,4W(160MHz)	?2a	Mot	(2N1693)
2N1564	Si-NPN	AF,80V,0,05A,0,6W,>30MHz	2a$	USA,Tix	BC140..141,BC300..301,2N1889..90..
2N1565	Si-NPN	AF,80V,0,05A,0,6W,>60MHz	2a$	USA,Tix	BC140..141,BC300..301,2N1889..90..
2N1566	Si-NPN	AF,80V,0,05A,0,6W,>60MHz	2a$	USA,Tix	BC140..141,BC300..301,2N1889..90..

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2N1566A	Si-NPN	=2N1566:0,1A,>100MHz	2a$	-	BC140..141,BC300..301,2N1889..90..
2N157	Ge-PNP	AF,Sw-Pow,60V,Ueb=30V,3A,20W,0,1MHz	23a$	USA	AUY19..20,2N2139..41,2N2144..46..
2N1572	Si-NPN	AF,125V,0,05A,0,6W,>30MHz	2a$	USA,Tix	BC300,2N1893(A),2SD755..756(A)..
2N1573	Si-NPN	AF,125V,0,05A,0,6W,>60MHz	2a$	USA,Tix	BC300,2N1893(A),2SD755..756(A)..
2N1574	Si-NPN	AF,125V,0,05A,0,6W,>60MHz	2a$	USA,Tix	BC300,2N1893(A),2SD755..756(A)..
2N157A	Ge-PNP	=2N157:90V	23a$	-	AUY28,AUY34,2N2141,2N2146..
2N158	Ge-PNP	=2N157:25W	-	USA	(AUY19..20,2N2139..41,2N2144..46,..)
2N1585	Ge-NPN	HF,25V,0,1A,0,3W,400MHz	2a	Cen	-
2N1586	Si-NPN	GenP,15V,0,025A,0,125W,>5MHz	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N1587	Si-NPN	=2N1586:30V	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N1588	Si-NPN	=2N1586:60V	?1a	USA,Tix	BC174,BC182,BC190,BC546..
2N1589	Si-NPN	GenP,15V,0,025A,0,125W,>5MHz	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N158A	Ge-PNP	=2N157:80V,Ueb=30V,25W	-		(AUY28,AUY34,2N2141,2N2146,..)
2N159	Ge-PNP	Sw,50V,Ueb=50V,0,01A,0,08W,>2MHz	?1a	Spr	(ASY77)
2N1590	Si-NPN	=2N1589:30V	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N1591	Si-NPN	=2N1589:60V	?1a	USA,Tix	BC174,BC182,BC190,BC546..
2N1592	Si-NPN	GenP,15V,0,025A,0,125W,>5MHz	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N1593	Si-NPN	=2N1592:30V	?1a	USA,Tix	BC168,BC183,BC238,BC548..
2N1594	Si-NPN	=2N1592:60V	?1a	USA,Tix	BC174,BC182,BC190,BC546..
2N1595	Thy-50Hz	50V,1A(Tc=80°),Igt/Ih<10/5mA	2a$	USA,Tag,Tho	BTX30/50,T1N100A,TAG1-50,S2600B..
2N1595A	Thy-50Hz	50V,1A(Tc=80°C),Igt/Ih<2/5mA	2a$	-	TAG2-50,MCR1906-2,TAG614-100
2N1596	Thy-50Hz	=2N1596:100V	2a$	-	BTX30/100,T1N100A,TAG1-100,S2600B,..
2N1596A	Thy-50Hz	=2N1595A:100V	2a$	-	TAG2-100,MCR1906-3,TAG614-100
2N1597	Thy-50Hz	=2N1596:200V	2a$	-	BTX30/200,T1N200A,TAG1-200,S2600B,..
2N1597A	Thy-50Hz	=2N1595A:200V	2a$	-	TAG2-200,MCR1906-4,TAG614-200
2N1598	Thy-50Hz	=2N1596:300V	2a$	-	BTX30/300,T1N300A,TAG1-300,S2600D,..
2N1598A	Thy-50Hz	=2N1595A:300V	2a$	-	TAG2-300,MCR1906-5,TAG614-300
2N1599	Thy-50Hz	=2N1596:400V	2a$	-	BTX30/400,T1N400A,TAG1-400,S2600D,..
2N1599A	Thy-50Hz	=2N1595A:400V	2a$	-	TAG2-400,MCR1906-6,TAG614-400
2N160(A)	Si-NPN	GenP,40V,0,025A,0,15W,B>9,4MHz	?1a	USA	BC167,BC182,BC237,BC547..
2N1605	Ge-NPN	AF,Sw,25V,0,1A,0,15W,>4MHz	2a	USA,Tix	ASY28..29,ASY73..75
2N1605A	Ge-NPN	=2N1605:40V	2a	-	-
2N1606	SI-PNP	Sw,10/10/10V,0,05A,0,1W,>7,2MHz	2a	Phc	-
2N1607	Si-PNP	Sw,10/10/10V,0,05A,0,1W,>10MHz	2a	Phc	-
2N1608	Si-PNP	Sw,10/10/10V,0,05A,0,1W,>25MHz	2a	Phc	-
2N1609	Ge-PNP	AF,Sw-Pow,80V,1,5A,4,5W,B>30	43a$	Del	-
2N161(A)	Si-NPN	=2N160:B>19,5MHz	?1a	USA	BC167,BC182,BC237,BC547..
2N1610	Ge-PNP	=2N1609:B>50	43a$	Del	-
2N1611	Ge-PNP	=2N1609:60V	43a$	Del	-
2N1612	Ge-PNP	=2N1609:60V,B>50	43a$	Del	-
2N1613	Si-NPN	75V1A0.8W60MHz	-		-
2N1613(S)	Si-NPN	GenP,75V,0,5A,0,8W,>60MHz	2a$	USA,EUR	BC140..141,BC300..301,2N1990..
2N1613A,L	Si-NPN	=2N1613:1A,1W	2a$	-	BC140..141,2N1990,2N2102,2N2405..
2N1613B	Si-NPN	=2N1613:120V,1A,1W	2a$	-	2N2102,2N2405,2N3019..20
2N1614	Ge-PNP	AF,Sw,65V,0,3A,0,24W,>0,5MHz	1a&	USA	ASY48,ASY77
2N1615	Si-NPN	AF,Sw,100V,0,2A,0,6W,>2MHz	2a$	USA	BC141,BC300,2N1889..90,2N1893(A),..
2N1616(/I)	Si-NPN	Sw,Pow,60V,5A,60W,>3MHz	49a$	USA,Tho	2N3487..92
2N1616A	Si-NPN	=2N1616:7,5A,85W	49a$	-	2N3487..92
2N1617(/I)	Si-NPN	Sw,Pow,80V,5A,60W,>3MHz	49a$	USA,Tho	2N3487..92
2N1617A	Si-NPN	=2N1617:7,5A,85W	49a$	-	2N3487..92
2N1618(/I)	Si-NPN	Sw,Pow,100V,5A,60W,>3MHz	49a$	USA,Tho	2N3488..89,2N3491..92
2N1618A	Si-NPN	=2N1618:7,5A,85W	49a$	-	2N3488..89,2N3491..92
2N1619	Si-NPN	Sw,Pow,60V,5A,60W,>3MHz	49a$	USA,Tho	2N3487..92
2N162(A)	Si-NPN	=2N160:B>19,8MHz	?1a	USA	BC167,BC182,BC237,BC547..
2N1620(/I)	Si-NPN	Sw,Pow,100V,5A,60W,>3MHz	49a$	USA,Tho	2N3488..89,2N3491..92
2N1622	Ge-NPN	AF,Sw,90V,0,12W,1MHz	2a	USA	-
2N1623	Si-PNP	GenP,50V,0,05A,0,25W	2a	USA	(BC212,BC257,BC307,BC557,..)
2N1624	Ge-NPN	AF,Sw,25V,0,15W,>5MHz	2a	USA	ASY28..29,ASY73..75
2N163(A)	Si-NPN	=2N160:B>39,6MHz	?1a	USA	BC167,BC182,BC237,BC547..
2N1631	Ge-PNP	HF,34V,10mA,0,08W,45MHz	1a	USA	AF124..126,AF200
2N1632	Ge-PNP	=2N1631:	2a	USA	AF124..126,AF200
2N1633	Ge-PNP	HF,34V,10mA,0,08W,40MHz	1a	USA	AF124..126,AF200
2N1634	Ge-PNP	=2N1633:	2a	USA	AF124..126,AF200
2N1635	Ge-PNP	HF,34V,10mA,0,08W,45MHz	1a	USA	AF124..126,AF200

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2N1636	Ge-PNP	=2N1635:	2a	USA	AF124..126,AF200
2N1637	Ge-PNP	HF,34V,10mA,0,08W,45MHz	2a	USA	AF124..126,AF200
2N1637/33	Ge-PNP	=2N1637:0,12W	5g	-	AF124..126,AF200
2N1638	Ge-PNP	HF,35V,10mA,0,08W,40MHz	2a	USa	AF124..126,AF200
2N1638/33	Ge-PNP	=2N1638:0,12W	5g	-	AF124..126,AF200
2N1639	Ge-PNP	HF,34V,10mA,0,08W,45MHz	2a	USA	AF124..126,AF200
2N1639/33	Ge-PNP	=2N1639:0,12W	2a	-	AF124..126,AF200
2N164(A)	Ge-NPN	AF/HF,15V,0,03A,0,06(A:0,1)W,>4MHz	2a	Csr,Etc	ASY28..29
2N1640	Si-PNP	Chopper,30V,0,05A,0,25W,B>6	2a	Ssi,Tdy	2N2946
2N1641	Si-PNP	Chopper,30V,0,05A,0,25W,B>10	2a	Ssi,Tdy	2N2946
2N1642	Si-PNP	Chopper,30V,0,05A,0,25W,B>15	2a	Ssi,Tdy	2N2946
2N1643	Si-PNP	Chopper,25V,0,05A,0,25W,B>10	2a	Ssi,Tdy	2N2946
2N1644(A)	Si-NPN	AF,Sw,60V,0,6W,>50MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N1645	Ge-PNP	HF-Dr,-/20V,0,3A,1W,600MHz	?2a	Wes	-
2N1646	Ge-PNP	HF/Sw,15V,0,05A,0,15W	2a	USA,Tix	AF106,AF109R,AF306
2N1647	Si-NPN	Sw,Pow,80V,5A,40W,>3MHz,B>15	?21	USA	2N5002,2N5004,2N5284..85,(BD243B,..)
2N1648	Si-NPN	=2N1647:120V	?21	USA	2N5284..85,(BD243C,BD539D,..)
2N1649	Si-NPN	Sw,Pow,80V,5A,40W,>3MHz,B>30	?21	USA	2N5002,2N5004,2N5284..85,(BD243B,..)
2N165	Ge-NPN	AF/HF,15V,0,02A,0,06W,5MHz	2a	Csr,Etc	ASY28..29
2N1650	Si-NPN	=2N1647:120V	?21	USA	2N5284..85,(BD243C,BD539D,..)
2N1651	Ge-PNP	AF,Sw-Pow,60V,25A,106W	23a$	USA,Mot	2N2285..87
2N1652	Ge-PNP	=2N1651:100V	23a$	USA,Mot	2N2286..87
2N1653	Ge-PNP	=2N1651:120V	23a$	USA,Mot	2N2287
2N1654	Si-PNP	GenP,100V,0,05A,0,25W,B>20	2a	USA	BF398,2SA893(A),2SA970,2SA1285(A),..
2N1655	Si-PNP	=2N1654:125V,B>10	2a	USA	BF398,2SA893(A),2SA970,2SA1285(A),..
2N1656	Si-PNP	=2N1654:125V,B>20	2a	USA	BF398,2SA893(A),2SA970,2SA1285(A),..
2N1657	Si-NPN	AF,Sw-Pow,60V,2A,55W	-	Ray,Tix	2N1722..23,(BD241,BD535,BD935,..)
2N1658(/13)	Ge-PNP	AF,Sw-Pow,80V,1A,15W	?37	USA	-
2N1659(/13)	Ge-PNP	=2N1658:60V	?37	USA	-
2N166	Ge-NPN	AF/HF,6V,0,02A,0,025W,5MHz	2a	Csr,Etc	ASY28..29
2N1660	Si-NPN	AF,Sw-Pow,60V,2A,85W	-	Ray,Tix	2N1722..23,(BD239A,BD241A,BD935..)
2N1661	Si-NPN	=2N1660:80V	-	Ray,Tix	2N1722..23,(BD239B,BD241B,BD937..)
2N1662	Si-NPN	=2N1660:100V	-	Ray,Tix	2N1722..23,(BD239C,BD241C,BD937..)
2N1663	Si-NPN	Sw,20V,0,1A,0,15W,-/65nS	2a	Phc	BSV89..92,BSX92..93,2N2368..69(A),..
2N1664	Ge-PNP	AF,Sw,45V,0,2A,0,2W,5MHz	2a$	USA	ASY48,ASY76..77
2N1665	Ge-PNP	HF,15V,0,05A,0,15W	2a$	USA	(AF109R,AF139,AF239(S))
2N1666	Ge-PNP	Sw,Pow,80V,6A,30W,B>15	23a$	Cen,Gpd	AL102..103,AUY28,2N3615..18..
2N1667	Ge-PNP	Sw,Pow,60V,6A,30W,B>35	23a$	Cen,Gpd	AL102..103,AUY28,2N3615..18..
2N1668	Ge-PNP	Sw,Pow,60V,6A,30W,B>20	23a$	Cen,Gpd	AL102..103,AUY28,2N3615..18..
2N1669	Ge-PNP	Sw,Pow,80V,6A,30W,B>20	23a$	Cen,Gpd	AL102..103,AUY28,2N3615..18..
2N167(A)	Ge-NPN	Sw,30V,0,075A,0,065W,8MHz,<60/220nS	?1a	Csr,Etc	ASY28
2N1670	Ge-PNP	AF,Sw,100V,0,12W,>10MHz	2a	USA	ACY39,2N2042..43
2N1671A	UJT-P	Ip<2SµA,Iv>8mA	5r,2p	Gen,Tho,Tix	-
2N1671AP	UJT-P	=2N1671A:Ip<12?A	5r,2p	-	-
2N1671AX	UJT-P	=2N1671A	5r,2p	-	-
2N1671B	UJT-P	=2N1671A:Ip<6?A	5r,2p	-	-
2N1671BX	UJT-P	=2N1671A:Ip<6?A	5r,2p	-	-
2N1671C	UJT-P	=2N1671A:Ip<2?A	5r,2p	-	2N2647
2N1671CX	UJT-P	=2N1671A:Ip<2?A	5r,2p	-	2N2647
2N1672(A)	Ge-NPN	AF,Sw,40V,0,12W,>2MHz	2a	USA	-
2N1673	Ge-PNP	HF,35V,10mA,0,08W,5MHz	5g	Cen	AF124..127,AF200
2N1674	Si-NPN	GenP,45V,0,025A,0,2W,>20MHz	2a	Sem,Tra	BC167,BC182,BC237,S47..
2N1675	Si-NPN	Sw,Pow,100V,10A,100W,>120MHz	?2a	Wes	(2SC2527)
2N1676	Si-PNP	Chopper,4,5/4,5/4,5V,0,05A,0,1W	2a$	USA	-
2N1677	Si-PNP	Chopper,4,5/4,5/4,5V,0,05A,0,1W	2a$	USA	-
2N1678	Ge-PNP	HF/Sw,60V,0,12W,>25MHz	2a	USA	AF118
2N1679	Si-NPN	AF-Driver,100V,1A,1W,>50MHz	2a$	Sty,Tix	BC141,BSW39,2N1990,2SC1069..
2N168(A)	Ge-NPN	HF,15V,0,02A,0,065W,6(A:8)MHz	?1a	Csr,Etc	ASY28..29
2N1680	Si-NPN	=2N1679:60V	2a$	Sty,Tix	BC140..141,BSW27..28,2SC1069..
2N1681	Ge-PNP	AF,30V,0,2A,0,18W,>5MHz	2a	USA	ASY26,ASY76..77
2N1682	Si-NPN	HF/Sw,25V,0,5W,>200MHz	2a$	USA	BFX96..97,BSY58,2N2218..19(A)..
2N1683	Ge-PNP	HF/Sw,13V,0,1A,0,15W,80MHz	2a	USA	ASZ21,2N705,2N960..67
2N1684	Ge-PNP	AF,Sw,25V,0,1A,0,1W	2a&	Syl	AC125..126,AC151,2SB54,2SB56
2N1685	Ge-NPN	AF,Sw,25V,0,1A,0,1W	2a&	Syl	AC127,AC176,AC187,ASY28..29

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2N1686	Thy-GTO	30V,1A,Igt/Ih<1/<5mA	2a	Sem,Sld	-
2N1687	Thy-GTO	=2N1686:60V	2a	-	-
2N1688	Thy-GTO	=2N1686:100V	2a	-	-
2N1689	Thy-GTO	=2N1686:200V	2a	-	-
2N169(A)	Ge-NPN	HF,15V,0,02A,0,065W,4(A:5)MHz	?1a	Csr,Etc	ASY28..29
2N1690	Si-NPN	Sw,Pow,80V,0,5A,40W	-	USA,Tix	(BD169,BD237,BD239B,BD241B,..)
2N1691	Si-NPN	=2N1690:120V	-	USA,Tix	(BD239C,BD241C,BD939,2SC2481,..)
2N1692	Ge-PNP	VHF-A/Dr,25V,0,25A,Pq>0,5W(160MHz)	49a	USA,Mot	(2N1561)
2N1693	Ge-PNP	VHF-A/Dr,25V,0,25A,Pq>0,4W(160MHz)	49a	USA,Mot	(2N1562)
2N1694	Ge-NPN	AF,Sw,20V,0,025A,0,075W,9MHz	2a$	USA	(ASY28..29,ASY73..75)
2N1699	Ge-PNP	HF,40V,0,1W,100MHz	-	Syl	AF106,AF109R,AF306
2N170	Ge-NPN	HF,6V,0,02A,0,025W,5MHz	?1a	Csr,Etc	ASY28..29
2N1700	Si-NPN	AF,Sw,60V,1A,5W(Tc=25°)	2a$	USA,Fer,Rca	BC140..141,BSX45..47,2N3107..10..
2N1701	Si-NPN	AF,Sw-Pow,60V,2,5A,25W(Tc=25°)	2a$	USA,Rca	(BD177,BD239A,BD437,BD935,..)
2N1702	Si-NPN	AF,Sw-Pow,60V,5A,75W	23a$	USA,Fer,Rca	BD245A,BDV91,BDX91,2N4914..15..
2N1703	Si-NPN	=2N1702:	38a$	USA,Rca	(BD245A,BDV91,BDX91,2N4914..15,..)
2N1704	Si-NPN	GenP,45V,0,05A,0,5W,5MHz	2a$	Csr,Etc	BC140..141,BC300..302,2N3053..
2N1705	Ge-PNP	AF-Driver,18V,0,4A,0,2W,4MHz	2a&	USA,Mot	AC128,AC152..153,AC188
2N1706	Ge-PNP	AF-Driver,25V,0,4A,0,2W,3MHz	2a&	USA,Mot	AC128,AC152..153,AC188
2N1707	Ge-PNP	AF-Driver,30V,0,4A,0,2W,3MHz	2a&	USA,Mot	AC128,AC152..153,AC188
2N1708	Si-NPN	Sw,25V,0,2A,0,3W,<40/75nS	2a$	USA,Fer,Mot	BSS11..12,BSX19..20,2N2368..69(A),..
2N1708A	Si-NPN	=2N1708:40V,0,5A	2a$	-	BSS10,BSX26,BSX39,2N3261
2N1709	Si-NPN	HF-Osc/Dr,75V,1,2A,13W,100MHz	2a$	USA	(BD139,BD230,2SC1398,2SC2690,..)
2N1710	Si-NPN	=2N1709:60V	2a$	USA	(BD137,BD228,2SC1398,2SC2690,..)
2N1711	Si-NPN	GenP,75V,0,5A,0,8W,>70MHz,B>100	2a$	USA,EUR	BC40..141,BC00..301,2N1990..
2N1711-46	Si-NPN	GenP,75V,0,5A,0,5W,>70MHz,B>100	2a$	-	BC140..141,2N1990,2N2102,2N2405..
2N1711A	Si-NPN	GenP,75V,1A,1W,>70MHz,B>100	2a$	-	BC40..141,2N1990,2N2102,2N2405..
2N1711B	Si-NPN	GenP,120V,1A,1W,>70MHz,B>20	2a$	-	2N2102,2N2405,2N3019..20
2N1711L	Si-NPN	GenP,75V,0,5A,0,5W,>70MHz,B>50	2a$	-	BC140..141,2N1990,2N2102,2N2405..
2N1711S	Si-NPN	GenP,75V,1A,0,8W,>70MHz,B>100	2a$	USA,EUR	BC140..141,BC300..301,2N1990..
2N1713	Ge-PNP	HF,30V,10mA,0,08W,>100MHz	1g	Rca,Sty	AF106,AF109R,AF306
2N1714	Si-NPN	GenP,90V,0,75A,0,8W,>16MHz,B>20	2a$	USA,Tix	BC141,BSS42..43,BSX46..47,2N5320..
2N1715	Si-NPN	=2N1714:150V	2a$	USA,Tix	BSS43,BSW68
2N1716	Si-NPN	GenP,90V,0,75A,0,8W,>16MHz,B>40	2a$	USA,Tix	BC141,BSS42..43,BSX46..47,2N5320..
2N1717	Si-NPN	=2N1714:150V,B>40	2a$	USA,Tix	BSS43,BSW68
2N1718	Si-NPN	=2N1714:	49a$	USA,Tix	(BD139,BD230,BD237,BD443,..)
2N1719	Si-NPN	=2N1715:	49a$	USA,Tix	(BD443A,BD524,2SC2481,2SC2690A,..)
2N172	Ge-NPN	HF,16V,5mA,0,065W,1MHz	?1a	Csr,Etc	-
2N1720	Si-NPN	=2N1716:	49a$	USA,Tix	(BD139,BD230,BD237,BD443,..)
2N1721	Si-NPN	=2N1717:	49a$	USA,Tix	(BD443A,BD524,2SC2481,2SC2690A,..)
2N1722(/I)	Si-NPN	Sw,Pow,120V,5A,100W,B>20	-	USA,Tix	(BD245C,BD545D,2SD718,2SD896,..)
2N1722A(/I)	Si-NPN	=2N1722:180V	-		(BD245E,2SD751)
2N1723	Si-NPN	=2N1722:B>50	-	USA,Tix	(BD245C,BD545D,2SD718,2SD896,..)
2N1724	Si-NPN	Sw,Pow,120V,5A,100W,B>20	49a$	USA,Mot,Tix	2N3489,2N3492
2N1724A	Si-NPN	=2N1724:180V	49a$	-	2N5542
2N1725	Si-NPN	=2N1724:B>50	49a$	USA,Mot,Tix	2N3489,2N3492
2N1726	Ge-PNP	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..126,AF200
2N1727	Ge-PNP	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..126,AF200
2N1728	Ge-PNP	HF,20V,0,05A,0,06W	2a	Etc,Spr	AF124..126,AF200
2N1729	Ge-PNP	AF,Sw,25V,0,3A,0,15W,<300/600nS	2a&	USA	ASY26..27,ASY76..77
2N173	Ge-PNP	AF,Sw-Pow,60V,Ueb=40MHz,15A,170W	38a$	Del,Mot,++	2N1981,2N2076,2N2080,2N2491..93
2N1730	Ge-NPN	AF,Sw,25V,0,3A,0,15W,<300/600nS	2a&	USA	ASY28..29,ASY73..75
2N1731	Ge-PNP	AF,Sw,30V,0,3A,0,15W	2a&	USA	ASY26,ASY76..77
2N1732	Ge-NPN	AF,Sw,30V,0,3A,0,15W	2a&	USA	ASY28,ASY73..75
2N174(A)	Ge-PNP	AF,Sw-Pow,80V,Ueb=60V,15A,150W	38a$	Del,Mot,++	2N1982,2N2075,2N2079,2N2492..93
2N1742	Ge-PNP	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1743	Ge-PNP	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1744	Ge-PNP	VHF,20V,0,05A,0,06W	2a	USA,Mot	AF139,AF239(S)
2N1745	Ge-PNP	HF,20V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1746	Ge-PNP	HF,20V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1747	Ge-PNP	HF,20V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1748(A)	Ge-PNP	HF,25V,0,05A,0,06W	2a	USA	AF106,AF109R,AF306
2N1749	Ge-PNP	HF,40V,0,01A,0,075W	2a	USA	AF106,AF109R,AF306
2N175	Ge-PNP	HF,10V,2mA,0,02W,0,85MHz	1a	USA	AF124..127,AF200

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2N1750	Ge-PNP	HF,14V,5mA,0,01SW	37d	Cbs,Phc	AF124..126,AF200
2N1751	Ge-PNP	Sw,Pow,80V,25A,106W	23a$	USA,Mot	2N1652..53,2N2286..87
2N1752	Ge-PNP	HF,12V,0,05A,0,06W	2a	Etc,Spr	AF124..126,AF200
2N1753	Ge-PNP	HF,30V,0,05A,0,03W	2a	Cen,Phc	AF124..126,AF200
2N1754	Ge-PNP	HF,13V,0,1A,0,05W	2a	Etc,Spr	(ASY26..27,ASY76..77)
2N1755	Ge-PNP	Sw,Pow,40V,3A,28W,B>30	-	Gpd,Stc	(AL102..103,AUY19..20,2N1529..48,..)
2N1756	Ge-PNP	=2N1755:60V	-	Gpd,Stc	(AL102..103,AUY19..20,2N1545..48,..)
2N1757	Ge-PNP	=2N1755:80V	-	Gpd,Stc	(AL102..103,AUY20,2N1546..48,..)
2N1758	Ge-PNP	=2N1755:100V	-	Gpd,Stc	(AL102..103,AUY34,2N1547..48,..)
2N1759	Ge-PNP	Sw,Pow,40V,3A,28W,B>60	-	Gpd,Stc	(AL102..103,AUY19..20,2N1529..48,..)
2N176	Ge-PNP	AF,Sw-Pow,40V,3A,90W	23a$	Mot,Stc,++	AD149,AUY19..20,2N2143..46..
2N1760	Ge-PNP	=2N1759:60V	-	Gpd,Stc	(AL102..103,AUY19..20,2N1545..48,..)
2N1761	Ge-PNP	=2N1759:80V	-	Gpd,Stc	(AL102..103,AUY20,2N1546..48,..)
2N1762	Ge-PNP	=2N1759:100V	-	Gpd,Stc	(AL102..103,AUY34,2N1547..48,..)
2N1763	Si-NPN	Sw,40V,0,05A,0,3W,<32/58	2a	Ray	2N3722..25,2SC1385
2N1764	Si-NPN	=2N1763:20V	2a	Ray	2N3722..25,2SC1385
2N1765	Thy-50Hz	400V,0,5A,Igt/Ih<10/<5mA	2a	Wes	2N1599,BTX30/400,T1N400,TAG1-400..
2N1768	Si-NPN	Sw,Pow,60V,3A,40W	-	USA	(BD241A,BD535,BD539A,BD935,..)
2N1769	Si-NPN	=2N1768:100V	-	USA	(BD241C,BD539C,BD937,2SD712,..)
2N1779	Ge-NPN	AF,Sw,25V,0,1A,0,1W,5MHz,B>20	2a	Etc,Syl	ASY28..29,ASY73..75
2N178	Ge-PNP	AF,Sw-Pow,30V,Ueb=20V,3A,40W	23a$	Mot,Stc,++	AD149,AUY19..20,2N2137..46..
2N1780	Ge-NPN	=2N1779:8MHz,B>30	2a	Etc,Syl	ASY28..29,ASY73..75
2N1781	Ge-NPN	=2N1779:6MHz,B>40	2a	Etc,Syl	ASY28..29,ASY73..75
2N1782	Ge-PNP	AF,Sw,30V,0,1A,0,1W,8MHz,B>30	2a	Etc,Syl	ASY26,ASY76..77
2N1783	Ge-NPN	=2N1779:30V,8MHz	2a	Etc,Syl	ASY28,ASY73..75
2N1784	Ge-PNP	=2N1782:12MHz,B>20	2a	Etc,Syl	ASY26,ASY76..77
2N1785	Ge-PNP	HF,10V,0,05A,0,045W,?50MHz	2a	USA	AF124..126,AF200
2N1786	Ge-PNP	HF,10V,0,05A,0,045W,?50MHz	2a	USA	AF124..126,AF200
2N1787	Ge-PNP	HF,15V,0,05A,0,045W,?50MHz	2a	USA	AF124..126,AF200
2N1788	Ge-PNP	HF,35V,0,05A,0,06W,100MHz	2a	USA	AF106,AF109R,AF306
2N1789	Ge-PNP	HF,35V,0,05A,0,06W,100MHz	2a	USA	AF106,AF109R,AF306
2N179	Ge-PNP	AF,Sw-Pow,-/40V,1A,10W(Tc=75°)	23a$	Mot	AD149,AUY19..20,2N2144..46..
2N1790	Ge-PNP	HF,35V,0,05A,0,06W,100MHz	2a	USA	AF106,AF109R,AF306
2N180	Ge-PNP	AF,Sw,30V,Ueb=30V,0,15W,0,7MHz	1a	Csr,Etc	ASY26,ASY76..77
2N1808	Ge-NPN	AF,Sw,25V,0,3A,0,15W,14MHz	2a&	USA,Tix	ASY28..29,ASY73..75
2N1809	Si-NPN	Sw,Pow,50V,10A,250W	53b$	Sem,Whs	-
2N181	Ge-PNP	=2N180:	?1ao	Csr,Etc	ASY26,ASY76..77
2N1810	Si-NPN	=2N1809:100V	53b$	Sem,Whs	-
2N1811	Si-NPN	=2N1809:150V	53b$	Sem,Whs	-
2N1812	Si-NPN	=2N1809:200V	53b$	Sem,Whs	-
2N1813	Si-NPN	=2N1809:250V	53b$	Sem,Whs	-
2N1814	Si-NPN	=2N1809:300V	53b$	Sem,Whs	-
2N1815	Si-NPN	=2N1809:350V	53b$	Sem,Whs	-
2N1816	Si-NPN	Sw,Pow,50V,15A,250W	53b$	Sem,Whs	-
2N1817	Si-NPN	=2N1716:100V	53b$	Sem,Whs	-
2N1818	Si-NPN	=2N1716:150V	53b$	Sem,Whs	-
2N1819	Si-NPN	=2N1716:200V	53b$	Sem,Whs	-
2N182	Ge-NPN	Sw,25V,Ueb=15V,0,1W,3,8MHz	1a	Csr,Etc	ASY28..29,ASY73..75
2N1820	Si-NPN	=2N1716:250V	53b$	Sem,Whs	-
2N1821	Si-NPN	=2N1716:300V	53b$	Sem,Whs	-
2N1822	Si-NPN	=2N1716:350V	53b$	Sem,Whs	-
2N1823	Si-NPN	Sw,Pow,50V,20A,250W	53b$	Sem,Whs	-
2N1824	Si-NPN	=2N1823:100V	53b$	Sem,Whs	-
2N1825	Si-NPN	=2N1823:150V	53b$	Sem,Whs	-
2N1826	Si-NPN	=2N1823:200V	53b$	Sem,Whs	-
2N1827	Si-NPN	=2N1823:250V	53b$	Sem,Whs	-
2N1828	Si-NPN	=2N1823:300V	53b$	Sem,Whs	-
2N1829	Si-NPN	=2N1823:350V	53b$	Sem,Whs	-
2N183	Ge-NPN	Sw,25V,Ueb=15V,0,1W,7,5MHz	1a	Csr,Etc	ASY28..29,ASY73..75
2N1830	Si-NPN	Sw,Pow,50V,25A,250W	53b$	Sem,Whs	-
2N1831	Si-NPN	=2N1830:100V	53b$	Sem,Whs	-
2N1832	Si-NPN	=2N1830:150V	53b$	Sem,Whs	-
2N1833	Si-NPN	=2N1830:200V	53b$	Sem,Whs	-
2N1834	Si-NPN	=2N1830:250V	53b$	Sem,Whs	-

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2N1835	Si-NPN	=2N1830:300V	53b$	Sem,Whs	-
2N1836	Si-NPN	=2N1830:350V	53b$	Sem,Whs	-
2N1837(A,B)	Si-NPN	AF,Sw,80V,0,5A,0,6W,<200/500nS	2a$	USA	BC140..141,BC300..301,2N2218..19A,..
2N1838	Si-NPN	AF,Sw,45V,0,5A,0,6W,<200/800nS	2a$	USA	BC140..141,BC300..301,2N2218..19..
2N1839(A)	Si-NPN	AF,Sw,45V,0,5A,0,6W,<200/600nS	2a$	USA	BC140..141,BC300..301,2N2218..19..
2N184	Ge-NPN	Sw,25V,Ueb=15V,0,1W,15MHz	1a	Csr,Etc	ASY28..29,ASY73..75
2N1840	Si-NPN	AF,Sw,25V,0,5A,0,6W,<500/1200nS	2a$	USA	BC140..141,BC300..301,2N2218..19..
2N1841	Si-NPN	AF,Sw-Pow,-/50V,13W,78MHz	?2a	Nsc	(BD139,BD230,BD379,2SC1398,..)
2N1842	Thy-50Hz	25V,10A(Tc=80°),Igt/Ih<80/40mA	21b$	USA,Tag,Tho	BTW39/50,BTW45/200R,TAG9N400..
2N1843	Thy-50Hz	=2N1843:50V	21b$	-	BTW39/50,BTW45/200R,TAG9N400..
2N1844	Thy-50Hz	=2N1843:100V	21b$	-	BTW39/100,BTW45/200R,TAG9N400..
2N1845	Thy-50Hz	=2N1843:150V	21b$	-	BTW39/200,BTW45/200R,TAG9N400..
2N1846	Thy-50Hz	=2N1843:200V	21b$	-	BTW39/200,BTW45/200R,TAG9N400..
2N1847	Thy-50Hz	=2N1843:250V	21b$	-	BTW39/300,BTW45/300R,TAG9N400..
2N1848	Thy-50Hz	=2N1843:300V	21b$	-	BTW39/300,BTW45/300R,TAG9N400..
2N1849	Thy-50Hz	=2N1843:400V	21b$	-	BTW39/400,BTW45/400R,TAG9N400..
2N185	Ge-PNP	AF/HF,20V,0,15A,0,15W	?1a	USA	AC125..126,AC151,ASY26..27
2N1850	Thy-50Hz	=2N1843:500V	21b$	-	BTW39/500,BTW45/500R,TAG9N600..
2N1853(/18)	Ge-PNP	Sw,18V,0,1A,0,15W,<800/900nS	2a	USA	(ASY26..27,ASY76..77)
2N1854	Ge-PNP	Sw,18V,0,1A,0,15W,>40MHz	2a	USA	(ASY26..27,ASY76..77)
2N186(A)	Ge-PNP	AF/HF,25V,0,2A,0,1(A:0,2W),B=24	1a&	USA	AC125..126,AC151..152
2N1864	Ge-PNP	HF,20V,0,05A,0,06W,?50MHz	2a	USA	AF124..126,AF200
2N1865	Ge-PNP	HF,20V,0,05A,0,06W,?180MHz	2a	USA	AF106,AF109R,AF306
2N1866	Ge-PNP	HF,35V,0,05A,0,06W,180MHz	2a	USA	AF106,AF109R,AF306
2N1867	Ge-PNP	HF,35V,0,05A,0,06W,180MHz	2a	USA	AF106,AF109R,AF306
2N1868	Ge-PNP	HF,35V,0,05A,0,06W,400MHz	2a	USA	AF139,AF239(S)
2N1869(A)	Thy-50Hz	15V,1,25A(Tc=100°),Igt/Ih<0,2/<5mA	2a	USA,Mot	2N2322,2N6332,TAG615-100,(MCR606-2)
2N187(A)	Ge-PNP	=2N186:B=36	1a&	USA	AC125..126,AC151..152
2N1870(A)	Thy-50Hz	=2N1869:30V	2a	-	2N2323,2N6333,TAG615-100,(MCR606-2)
2N1871(A)	Thy-50Hz	=2N1869:60V	2a	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N1872(A)	Thy-50Hz	=2N1869:100V	2a	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N1873(A)	Thy-50Hz	=2N1869:150V	2a	-	2N2325,2N6335,TAG615-200,(MCR606-4)
2N1874(A)	Thy-50Hz	=2N1869:200V	2a	-	2N2326,2N6336,TAG615-200,(MCR606-4)
2N1875(A)	Thy-50Hz	=2N1869:Igt/Ih<0,02/<3mA	2a	USA,Mot	2N2322A
2N1876(A)	Thy-50Hz	=2N1870:Igt/Ih<0,02/<3mA	2a	-	2N2323A
2N1877(A)	Thy-50Hz	=2N1871:Igt/Ih<0,02/<3mA	2a	-	2N2324A
2N1878(A)	Thy-50Hz	=2N1872:Igt/Ih<0,02/<3mA	2a	-	2N2324A
2N1879(A)	Thy-50Hz	=2N1873:Igt/Ih<0,02/<3mA	2a	-	2N2325A
2N188(A)	Ge-PNP	=2N186:B=54	1a&	USA	AC125..126,AC151..152
2N1880(A)	Thy-50Hz	=2N1874:Igt/Ih<0,02/<3mA	2a	-	2N2326A
2N1881	Thy-50Hz	30V,1A(Tc=100°),Igt/Ih<2,5/<10mA	2a$	USA,Mot	TAG2-50,MCR1906-2,TAG614-100
2N1882	Thy-50Hz	=2N1881:60V	2a$	-	TAG2-100,MCR1906-3,TAG614-100
2N1883	Thy-50Hz	=2N1881:100V	2a$	-	TAG2-100,MCR1906-3,TAG614-100
2N1884	Thy-50Hz	=2N1881:150V	2a$	-	TAG2-200,MCR1906-4,TAG614-200
2N1885	Thy-50Hz	=2N1881:200V	2a$	-	TAG2-200,MCR1906-4,TAG614-200
2N1886	Si-NPN	Sw,Pow,60V,3A,40W	21	USA	(BD241A,BD535,BD539A,BD935,..)
2N1889	Si-NPN	AF,Sw,100V,0,5A,0,8W,>50MHz,B>40	2a$	USA,EUR	BC141,BC300,2N1893(A),2N1990..
2N189	Ge-PNP	AF/HF,25V,0,2A,0,2W,B=32,0,8MHz	1a&	USA	AC125..126,AC151..152
2N1890(S)	Si-NPN	=2N1889:>60MHz,B>100	2a$	USA,EUR	BC141,BC300,2N1893(A),2N1990..
2N1891	Ge-NPN	AF,Sw,25V,0,3A,0,15W,>5MHz	2a&	USA,Tix	ASY28..29,ASY73..75
2N1892	Ge-PNP	AF,Sw,30V,0,3A,0,15W,>5MHz	2a&	USA,Tix	ASY26..27,ASY76..77
2N1893(L,S)	Si-NPN	AF,Sw,120V,0,5A,0,8W,70MHz	2a$	USA,EUR	BC300,BSY55..56,2N2102,2N2405..
2N1893A	Si-NPN	=2N1893:140V,>100MHz	2a$	-	BSS43,BSW68,2N3019..20
2N1894	Si-NPN	AF,Sw-Pow,60V,2A,85W	49a$	Ray	-
2N1895	Si-NPN	=2N1894:80V	49a$	Ray	-
2N1896	Si-NPN	AF,Sw-Pow,60V,2A,85W	49a$	Ray	-
2N1897	Si-NPN	=2N1896:80V	49a$	Ray	-
2N1898	Si-NPN	=2N1896:100V	49a$	Ray	-
2N1899	Si-NPN	AF,Sw-Pow,140V,10A(ss),125W,B>10	-	USA	-
2N190	Ge-PNP	=2N189:a=42,1MHz	1a&	USA	AC125..126,AC151..152
2N1900	Si-NPN	=2N1899:B>8	-	USA	-
2N1901	Si-NPN	=2N1899:B>20	-	USA	-
2N1902	Si-NPN	=2N1899:	49a	USA	-
2N1903	Si-NPN	=2N1899:B>8	49a	USA	-

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2N1904	Si-NPN	=2N1899: B>20	49a	USA	-
2N1905	Ge-PNP	Sw, Pow, 100V, 6A, 30W(Tc=55°)	23a$	RCA	AL102..103, AU108, 2N5324..25
2N1906	Ge-PNP	=2N1905: 130V	23a$	USA, Rca, Sgs	AL102, AU110, AU210, 2N5324..25
2N1907(A)	Ge-PNP	Sw, Pow, 100V, 20A, 60W(Tc=70°)	23a$	TI	2N1652..53, 2N2286..87
2N1908(A)	Ge-PNP	=2N1907: 130V	23a$	USA, Tix	2N1653, 2N2287
2N191	Ge-PNP	=2N189: a=67, 1,2MHz	1a&	USA	AC125..126, AC151..152
2N1917	Si-PNP	Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	-
2N1918	Si-PNP	Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	-
2N1919	Si-PNP	Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	-
2N192	Ge-PNP	=2N189: a=90, 1,5MHz	1a&	USA	AC125..126, AC151..152
2N1920	Si-PNP	Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	-
2N1921	Si-PNP	Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	-
2N1922	Si-PNP	Chopper, 80/80/80V, 0,05A, 0,25W	2a	USA	-
2N1923	Si-NPN	GenP, 85V, 0,06A, 0,75W, 90MHz	2a$	Tix, Sty	BC141, BC300..301, BC546, 2N1889..90..
2N1924	Ge-PNP	AF, Sw, 60V, 0,5A, 0,225W, 1,5MHz, B>34	2a&	USA, Mot, Tix	ASY77
2N1925	Ge-PNP	=2N1924: 2,5MHz, B>53	2a&	USA, Mot, Tix	ASY77
2N1926	Ge-PNP	=2N1924: 3MHz, B>72	2a&	USA, Mot, Tix	ASY77
2N193	Ge-NPN	HF, 18V, 0,05A, 0,15W, 3MHz	?1a	USA	ASY28..29, ASY73..75
2N1936	Si-NPN	AF, Sw-Pow, 125/60V, 20A(ss), 200W	49a$	USA, Thi, Tix	2N2817..18, 2N2821..22, 2N5539
2N1937	Si-NPN	=2N1936: 125/80V	49a$	USA, Tho, Tix	2N2817..18, 2N2821..22, 2N5539
2N194(A)	Ge-NPN	HF, 18V, 0,1A, 0,05W, 3MHz	?1a	USA	ASY28..29, ASY73..75
2N1940	Ge-PNP	HF-Pow, 30V, 0,25A, 3,5W, >350MHz	49a	Mot, Sty	-
2N1941	Si-NPN	AF-Driver, 45V, 1A, 0,6W, >60MHz	2a$	Sty	BC140..141, 2N1990, 2N2102, 2N2405..
2N1942	Ge-PNP	AF, Sw, 20V, 0,5A, 0,2W, >5MHz	2a	USA	ASY76..77
2N1943	Si-NPN	AF, 60V, 0,5A, 0,8W	2a$	USA	BC140..141, BC300..302, 2N3053..
2N1944	Si-NPN	AF, Sw, 20V, 1A, 0,6W, >60MHz, B>150	2a$	USA	BC140..141, 2N1990, 2N2101, 2N2405..
2N1945	Si-NPN	=2N1944: 30V	2a$	USA	BC140..141, 2N1990, 2N2101, 2N2405..
2N1946	Si-NPN	=2N1944: 40V	2a$	USA	BC140..141, 2N1990, 2N2101, 2N2405..
2N1947	Si-NPN	AF, Sw, 20V, 1A, 0,6W, >60MHz, B>500	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N1948	Si-NPN	=2N1947: 30V	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N1949	Si-NPN	=2N1947: 40V	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N195	Ge-PNP	GenP, 15V, 0,03A, 0,1W, 1MHz	2a*	Tra	AC125..126, AC151
2N1950	Si-NPN	AF, Sw, 20V, 1A, 0,6W, >60MHz, B>250	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N1951	Si-NPN	=2N1950: 30V	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N1952	Si-NPN	=2N1950: 40V	2a$	USA	(BC140..141, 2N1990, 2N2101, 2N2405,..)
2N1953	Si-NPN	AF, Sw, 20V, 1A, 0,6W, >40MHz	2a$	USA	BC140..141, 2N1990, 2N2101, 2N2405..
2N1954	Ge-PNP	AF, Sw, 60/20V, 0,2A, 0,2W	2a$	USA	ASY77
2N1955	Ge-PNP	AF, Sw, 60/18V, 0,2A, 0,2W	2a$	USA	ASY77
2N1956	Ge-PNP	AF, Sw, 60/16V, 0,2A, 0,2W	2a$	USA	ASY77
2N1957	Ge-PNP	AF, Sw, 60/14V, 0,2A, 0,2W	2a$	USA	ASY77
2N1958	Si-NPN	Sw, 60V, 0,5A, 0,6W, <65/45nS, B>20	2a$	USA	BSS27, BSV77, BSV95, 2N5189..
2N1958A	Si-NPN	=2N1958: 1A, <60/45nS	2a$	-	BSS27, BSV77, BSV95, 2N5189..
2N1959	Si-NPN	Sw, 60V, 0,5A, 0,6W, <65/45nS, B>40	2a$	USA	BSS27, BSV77, BSV95, 2N5189..
2N1959A	Si-NPN	=2N1959: 1A, <60/45nS	2a$	-	BSS27, BSV77, BSV95, 2N5189..
2N196	Ge-PNP	GenP, 30V, 0,03A, 0,1W, 0,8MHz	2a*	Tra	AC125..126, AC151
2N1960(/46)	Ge-PNP	Sw, 15V, 0,2A, 0,15W, <60/70nS	2a$	Nsc, Syl	2N964(A), 2N2635, 2N2955..57
2N1961(/46)	Ge-PNP	Sw, 12V, 0,2A, 0,15W, <75/110nS	2a$	Nsc, Syl	2N960..2N967, 2N2635, 2N2955..57
2N1962(/46)	Si-NPN	GenP, 40V, 0,2A, 0,4W, <18/30nS	2a$	Syl	BSS10..11, BSX19..20, 2N2368..69(A),..
2N1963(/46)	Si-NPN	GenP, 30V, 0,2A, 0,4W, <20/40nS	2a$	Syl	BSS10..11, BSX19..20, 2N2368..69(A),..
2N1964(/46)	Si-NPN	GenP, 60V, 0,5A, 0,4W, <65/45nS	2a$	Syl	2N4014
2N1965(/46)	Si-NPN	GenP, 60V, 0,5A, 0,4W, <65/45nS	2a$	Syl	2N4014
2N1966..1968	Opto	-		-	-
2N1969*	Ge-PNP	AF, Sw, 30V, 0,4A, 0,15W, >10MHz	2a	USA	ASY76..77
2N197	Ge-PNP	GenP, 30V, 0,03A, 0,1W, 0,7MHz	2a*	Tra	AC125..126, AC151
2N1970	Ge-PNP	AF, Sw-Pow, 100V, 15A, 170W	38a$	USA, Mot	2N2493
2N1971	Ge-PNP	AF, Sw-Pow, 80V, 4A, 38W	23a$	USA	AL102..103, AUY28, 2N1546..48,.
2N1972	Si-NPN	GenP, 60V, 1A, 0,8W, >50MHz	2a$	USA, Fch	BC140..141, 2N1990, 2N2102, 2N2405..
2N1973	Si-NPN	AF, Sw, 100V, 0,8W, >60MHz, B>75	2a$	USA, Fch, Tix	BC141, BC300, 2N1889..90, 2N1990..
2N1974	Si-NPN	AF, Sw, 100V, 0,8W, >50MHz, B>35	2a$	USA, Fch, Tix	BC141, BC300, 2N1889..90, 2N1990..
2N1975	Si-NPN	AF, Sw, 100V, 0,8W, >40MHz, B>15	2a$	USA, Fch, Tix	BC141, BC300, 2N1889..90, 2N1990..
2N1978	Si-NPN	AF, Sw-Pow, 60V, 30W(Tc=100°), >40MHz	?37a$	Fch, Sgs	-
2N198	Ge-PNP	GenP, 30V, 0,03A, 0,1W, 0,6MHz	2a*	Tra	AC125..126, AC151
2N1980	Ge-PNP	AF, Sw-Pow, 50V, 15A, 170W	38a$	USA, Mot	2N2075..77, 2N2079..81, 2N2490..93
2N1981	Ge-PNP	AF, Sw-Pow, 70V, 15A, 170W	38a$	USA, Mot	2N2075..76, 2N2079..80, 2N2492..93

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2N1982	Ge-PNP	AF,Sw-Pow,90V,15A,170W	38a$	USA,Mot	2N2493
2N1983	Si-NPN	GenP,50V,1A,0,6W,>40MHz,B>80	2a$	USA,Mot,Sgs	BC140..141,2N1990,2N2102,2N2405..
2N1984	Si-NPN	=2N19B3:a>40	2a$	USA,Mot,Sgs	BC140..141,2N1990,2N2102,2N2405..
2N1985	Si-NPN	=2N1983:a>20	2a$	USA,Sgs	BC140..141,2N1990,2N2102,2N2405..
2N1986	Si-NPN	GenP,50V,1A,0,6W,>40MHz,B>60	2a$	USA,Sgs	BC140..141,2N1990,2N2102,2N2405..
2N1987	Si-NPN	=2N1986:B>20	2a$	USA,Sgs	BC140..141,2N1990,2N2102,2N2405..
2N1988	Si-NPN	GenP,100V,1A,0,6W,>40MHz,B>35	2a$	USA,Sgs	BC141,2N1990,2N2102,2N2405..
2N1989	Si-NPN	=2N1988:B>20	2a$	USA,Sgs	BC141,2N1990,2N2102,2N2405..
2N199	Ge-PNP	GenP,30V,0,03A,0,1W,0,5MHz	2a*	Tra	AC125..126,AC151
2N1990(N,R,W)	Si-NPN	=2N1990(S):0,25..0,3W	2a$	-	BC639,2N3700..01,2SD667,2SD774..
2N1990(S)	Si-NPN	NIx,100V,1A,0,6W	2a$	USA,EUR,Mic	BC141,2N1990,2N2102,2N2405..
2N1991(S)	Si-PNP	AF,Sw,30V,0,6A,0,6W,>40MHz	2a$	USA,Mot,Sgs	BC160..161,BC303..304,2N2303..
2N1992	Si-NPN	Sw,-/15V,0,05A,0,35W,430MHz	2a$	Nsc	BSV89..92,BSX92..93,2N2368..69(A),..
2N1993	Ge-NPN	AF,Sw,30/18/30V,0,3A,0,15W,>3MHz	2a	USA,Tix	(ASY28,ASY73..75)
2N1994	Ge-NPN	Sw,Bidirectional,30V,0,3A,0,15W	2a&	USA,Tix	-
2N1995	Ge-NPN	=2N1994:25V	2a&	USA,Tix	-
2N1996	Ge-NPN	=2N1994:20V	2a&	USA,Tix	-
2N1997	Ge-PNP	AF,Sw,45V,0,5A,0,25W,>3MHz	2a	USA,Tix	ASY77
2N1998	Ge-PNP	=2N1997:35V	2a	USA,Tix	ASY76..77
2N1999	Ge-PNP	=2N1997:30V	2a	USA,Tix	ASY76..77
2N200	Ge-PNP	GenP,36V,0,1A,0,1W,1MHz	2a*	Tra	AC125..126,AC151
2N2000	Ge-PNP	Sw,50V,1A,0,3A,>2MHz	2a&	USA,Tix	-
2N2001	Ge-PNP	=2N2000:30V	2a&	USA,Tix	-
2N2002	Si-PNP	Chopper,30/5/30V,0,1A,0,25W	2a	USA	2N2946
2N2003	Si-PNP	Chopper,30/5/30V,0;1A,0,25W	2a	USA	2N2946
2N2004	Si-PNP	Chopper,50/15/50V,0,1A,0,25W	2a	USA	2N2946
2N2005	Si-PNP	Chopper,50/15/50V,0,1A,0,25W	2a	USA	2N2946
2N2006	Si-PNP	Chopper,60/35/60V,0,1A,0,25W	2a	USA	-
2N2007	Si-PNP	Chopper,60/35/60V,0,1A,0,25W	2a	USA	-
2N2008	Si-NPN	GenP,175V,0,5A,0,8W,>40MHz	2a$	USA,Fch	BSS48..49,2N3439..40
2N2009	Thy-50Hz	25V,1,3A(Tc=80°C),Igt/Ih<0,2/<5mA	2a$	USA,Mot,Tag	2N2322,2N6332,TAG615-100,(MCR606-2)
2N2010	Thy-50Hz	=2N2009:50V	2a$	-	2N2323,2N6333,TAG615-100,(MCR606-2)
2N2011	Thy-50Hz	=2N2009:100V	2a$	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N2012	Thy-50Hz	=2N2009:200V	2a$	-	2N2326,2N6335,TAG615-200,(MCR606-4)
2N2013	Thy-50Hz	=2N2009:300V	2a$	-	2N2328,2N6336,TAG615-300,(MCR606-5)
2N2014	Thy-50Hz	=2N2009:400V	2a$	-	2N2329,2N6337,TAG615-400,(MCR606-6)
2N2015	Si-NPN	Sw,Pow,100V,10A,150W	38a$	Ssi,Stc	-
2N2016	Si-NPN	=2N2015:130V	38a$	Ssi,Stc	-
2N2017	Si-NPN	GenP,80V,1A,1W	2a$	USA,Nsc	BC140..141,2N1990,2N2102,2N2405..
2N2018	Si-NPN	Sw,Pow,150V,2A,40W,10MHz	?21	USA	-
2N2019	Si-NPN	Sw,Pow,200V,2A,40W,10MHz	?21	USA	-
2N2020	Si-NPN	Sw,Pow,150V,2A,40W,10MHz	?21	USA	-
2N2021	Si-NPN	Sw,Pow,200V,2A,40W,10MHz	?21	USA	-
2N2022	Ge-PNP	Sw,15V,0,05A,>250MHz,<60/-nS	2a$	Wes	(ASZ21,2N705,2N964(A))
2N2032	Si-NPN	Sw,Pow,45V,5A,85W	-	USA,Tix	(BD245,BD543,BDS45A,BDV91,..)
2N2033	Si-NPN	Sw,Pow,80V,3A,5W(Tc=25°)	2a$	USA	BSX64,BUY41,2N4238..39,2SC2214
2N2033S	Si-NPN	=2N2033:8,5W	49a$	-	(BD179,BD241B,BD441,BD619,..)
2N2034	Si-NPN	Sw,Pow,80V,3A,5W(Tc=25°)	2a$	USA	BSX64,BUY41,2N4238..39,2SC2214
2N2034S	Si-NPN	=2N2034:8,5W	49a$	-	(BD179,BD241B,BD441,BD619,..)
2N2035	Si-NPN	Sw,Pow,80V,3A,14W(Tc=25°)	2a$	USA	(BD179,BD241B,BD441,BD619,..)
2N2036	Si-NPN	Sw,Pow,80V,3A,10W(Tc=25°)	43a$	USA	(BD179,BD241B,BD441,BD619,..)
2N2038	Si-NPN	AF-Driver,45V,0,5A,0,6W(Ta=100°),B>12	2a$	USA	BC140..141,BC300..302,2N3053..
2N2039	Si-NPN	=2N3038:75V	2a$	USA	BC140..141,BC300..301,2N1613..
2N204	Ge-PNP	GenP,36V,Ueb=12V,0,1A,0,1W,B>50	2a*	Tra	AC125..126,AC151
2N2040	Si-NPN	AF-Driver,45V,0,5A,0,6W(Ta=100°),B>30	2a$	USA	BC140..141,BC300..302,2N3053..
2N2041	Si-NPN	=2N3040:75V	2a$	USA	BC140..141,BC300..301,2N1613..
2N2042(A)	Ge-PNP	AF,Sw,105V,0,2A,0,2W,B>20	2a	USA,Mot	ACY39,2N398
2N2043(A)	Ge-PNP	AF,Sw,105V,0,2A,0,2W,B>20	2a	USA,Mot	ACY39,2N398
2N2048	Ge-PNP	Sw,20V,0,1A,0,15W,>150MHz	2a	USA	2N2955..57
2N2048A	Ge-PNP	=2N2048:30V	2a	-	2N2955..57
2N2049	Si-NPN	GenP,75V,0,5A,0,8W,>50MHz	2a$	USA,Fch	BC140..141,BC300..302,2N1711..
2N205	Ge-PNP	=2N204:a>15	2a*	Tra	AC125..126,AC151
2N2059	Ge-PNP	Sw,10V,0,05A,0,06W,<8/25nS	2a	Cen	(ASZ21,2N705,2N960..67,2N2955..57)
2N206	Ge-PNP	AF,30V,Ueb=12V,0,05A,75mW,0,78MHz	2a	Etc	AC125..126,AC151

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2N2060(A,B)	Si-NPN	Dual,100V,0,5A,0,6W,>60MHz	81bs	USA,EUR	BFX70..72,2N2223
2N2061	Ge-PNP	Sw,Pow,20V,3A,40W	23a$	ITT	AL102..103,AUY28,2N1529..48..
2N2061A	Ge-PNP	=2N2061:5A,90W	23a$	-	AL102..103,AUY28,2N1529..48..
2N2062	Ge-PNP	Sw,Pow,20V,3A,40W	23a$	ITT	AL102..103,AUY28,2N1529..48..
2N2062A	Ge-PNP	=2N2062:5A,90W	23a$	-	AL102..103,AUY28,2N1529..48..
2N2063	Ge-PNP	Sw,Pow,40V,3A,35W	23a$	ITT	AL102..103,AUY28,2N1529..48..
2N2063A	Ge-PNP	=2N2063:5A,90W	23a$	-	AL102..103,AUY28,2N1529..48..
2N2064	Ge-PNP	Sw,Pow,40V,3A,35W	23a$	ITT	AL102..103,AUY28,2N1529..48..
2N2064A	Ge-PNP	=2N2064:5A,90W	23a$	-	AL102..103,AUY28,2N1529..48..
2N2065	Ge-PNP	Sw,Pow,80V,3A,35W	23a$	USA,Itt	AL102..103,AUY28,2N1546..48..
2N2065A	Ge-PNP	=2N2065:5A,90W	23a$	-	AL102..103,AUY28,2N1546..48..
2N2066	Ge-PNP	Sw,Pow,80V,3A,35W	23a$	USA,Itt	AL102..103,AUY28,2N1546..48..
2N2066A	Ge-PNP	=2N2066:5A,90W	23a$	-	AL102..103,AUY28,2N1546..48..
2N2067	Ge-PNP	AF,Sw-Pow,40V,3A,28W	-	USA	-
2N2068	Ge-PNP	=2N2067:80V	-	USA	-
2N2069	Ge-PNP	AF,Sw-Pow,40V,12A,75W	23a$	Cen	2N1549..60
2N207(A,B)	Ge-PNP	AF,12/12/12V,0,02A,85mW,2MHz	2a	USA	ASY26..27
2N2070	Ge-PNP	=2N2069:80V	23a$	Cen	2N1551..52,2N1555..56,2N1559..60
2N2071	Ge-PNP	=2N2069	23a$	Cen	2N1549..60
2N2072	Ge-PNP	=2N2069:80V	23a$	Cen	2N1551..52,2N1555..56,2N1559..60
2N2075(A)	Ge-PNP	Sw,Pow,80V,15A,170W,B>20	38a$	USA,Mot	2N1982,2N2492..93
2N2076(A)	Ge-PNP	=2N2075:70V	38a$	USA,Mot	2N1981..82,2N2492..93
2N2077(A)	Ge-PNP	=2N2075:50V	38a$	USA,Mot	2N1980..82,2N2490..93
2N2078(A)	Ge-PNP	=2N2075:40V	38a$	USA,Mot	2N1980..82,2N2490..93
2N2079(A)	Ge-PNP	Sw,Pow,80V,15A,170W,B>35	38a$	USA,Mot	2N1982,2N2492..93
2N2080(A)	Ge-PNP	=2N2079:70V	38a$	USA,Mot	2N1981..82,2N2492..93
2N2081(A)	Ge-PNP	=2N2079:50V	38a$	USA,Mot	2N1980..82,2N2490..93
2N2082(A)	Ge-PNP	=2N2079:40V	38a$	USA,Mot	2N1980..82,2N2490..93
2N2083	Ge-PNP	HF,30V,10mA,0,06W,>30MHz	1g	Cen,Sty	AF124..126,AF200
2N2084	Ge-PNP	HF,40V,10mA,0,125W,>100MHz	5g	Spe,Sty	AF106,AF109R,AF306
2N2085	Ge-NPN	AF,Sw,33V,0,5A,0,15W,8MHz	2a	USA	ASY28,ASY73..75
2N2086	Si-NPN	AF,Sw,120V,0,5A,0,6W,>150MHz,B>20	2a$	USA	BC300,2N1893(A),2N2102,2N2405..
2N2087	Si-NPN	=2N2086:B>40	2a$	USA	BC300,2N1893(A),2N2102,2N2405..
2N2089	Ge-PNP	HF,20V,10mA,0,1W,>44MHz	1g	Amp	AF124..126,AF200
2N2090	Ge-PNP	HF,20V,10mA,0,1W,>44MHz	1g	Amp	AF124..126,AF200
2N2091	Ge-PNP	HF,20V,10mA,0,1W,>44MHz	1g	Amp	AF124..126,AF200
2N2092	Ge-PNP	HF,20V,10mA,0,1W,>30MHz	1g	Amp	AF124..126,AF200
2N2093	Ge-PNP	HF,25V,10mA,0,1W,>30MHz	1g	Amp	AF124..126,AF200
2N2094	Si-NPN	GenP,60/40V,0,6W,>200MHz	2a$	Spr	BFR10,BFX96..97,2N3722..23,2SC1385,..
2N2094A	Si-NPN	=2N2094:60/60V	2a$	-	BFR10,BFX96..97,2N3722..23,2SC1385,..
2N2095	Ge-PNP	HF-Pow,30V,0,3A,>500MHz	49a$	Ssi	-
2N2096	Ge-PNP	Sw,25V,0,5A,0,5W,-/130nS	49a$	USA,Mot	2N1494
2N2097	Ge-PNP	Sw,40V,0,5A,0,5W,-/90nS	49a$	USA,Mot	2N1496
2N2098	Ge-PNP	HF,30V,0,3A,1W,>500MHz	2a$	Spr	-
2N2099	Ge-PNP	=2N2096:0,3W	2a$	USA,Mot	2N1495
2N21(A)	Ge-PNP	AF,Sw,100V,0,04A,0,12W,2MHz	?1a	Wes	(ACY39,2N2042..43)
2N2100(A)	Ge-PNP	=2N2097:0,3W	2a$	USA,Mot	2N1495
2N2101	Si-NPN	Sw,Pow,60V,3A,75W	49a$	USA	2N3487..92
2N2102(A,L,S)	Si-NPN	AF,Sw,120V,1A,1W,>120MHz	2a$	USA,EUR	BSS42..43,BSX47,2N2405,2N3019..20..
2N2104	Si-PNP	AF,Sw,50V,0,6A,0,8W,60MHz,B>25	2a$	old	BC161,BC303..304,2N2303,2SA606..
2N2105	Si-PNP	=2N2104:B>15	2a$	old	BC161,BC303..304,2N2303,2SA606..
2N2106	Si-NPN	AF,Sw,60V,0,5A,1W,B>12	2a$	USA	BC140..141,BC300..302,2N3053..
2N2107	Si-NPN	=2N2106:B>30	2a$	USA	BC140..141,BC300..302,2N3053..
2N2108	Si-NPN	=2N2106:B>75	2a$	-	BC140..141,BC300..302,2N3053..
2N2109	Si-NPN	Sw,Pow,50V,30A,250W(Tc=60°)	21b$	USA,Whs	2N6324..25
2N211	Ge-NPN	AF/HF,-/10V,0,05A,0,05W,3MHz	?1a	Csr,Etc	ASY28..29,ASY73..75
2N2110	Si-NPN	=2N2109:100V	21b$	USA,Whs	2N6324..25
2N2111	Si-NPN	=2N2109:150V	21b$	USA,Whs	2N6324..25
2N2112	Si-NPN	=2N2109:200V	21b$	USA,Whs	2N6324..25
2N2113	Si-NPN	=2N2109:250V	21b$	USA,Whs	2N6324..25
2N2114	Si-NPN	=2N2109:300V	21b$	USA,Whs	2N6324..25
2N2115	Si-NPN	=2N2109:350V	21b$	USA,Whs	2N6324..25
2N2116	Si-NPN	Sw,Pow,50V,30A,250W(Tc=60°)	21b$	USA,Whs	2N6324..25
2N2117	Si-NPN	=2N2116:100V	21b$	USA,Whs	2N6324..25

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2N2118	Si-NPN	=2N2116:150V	21b$	USA,Whs	2N6324..25
2N2119	Si-NPN	=2N2116:200V	21b$	USA,Whs	2N6324..25
2N212	Ge-NPN	AF,18V,0,1A,0,15W,>4MHz	?1a	Csr,Etc	ASY28..29,ASY73..75
2N2120	Si-NPN	=2N2116:250V	21b$	USA,Whs	2N6324..25
2N2121	Si-NPN	=2N2116:300V	21b$	USA,Whs	2N6324..25
2N2122	Si-NPN	=2N2116:350V	21b$	USA,Whs	2N6324..25
2N2123	Si-NPN	Sw,Pow,50V,30A,250W(Tc=60°)	21b$	USA,Whs	2N6324..25
2N2124	Si-NPN	=2N2123:100V	21b$	USA,Whs	2N6324..25
2N2125	Si-NPN	=2N2123:150V	21b$	USA,Whs	2N6324..25
2N2126	Si-NPN	=2N2123:200V	21b$	USA,Whs	2N6324..25
2N2127	Si-NPN	=2N2123:250V	21b$	USA,Whs	2N6324..25
2N2128	Si-NPN	=2N2123:300V	21b$	USA,Whs	2N6324..25
2N2129	Si-NPN	=2N2123:350V	21b$	USA,Whs	2N6324..25
2N213(A)	Ge-NPN	AF,40V,0,1A,0,05W	?1a	Csr,Etc	(AC127)
2N2130	Si-NPN	Sw,Pow,50V,30A,250W(Tc=60°)	21b$	USA,Whs	2N6324..25
2N2131	Si-NPN	=2N2130:100V	21b$	USA,Whs	2N6324..25
2N2132	Si-NPN	=2N2130:150V	21b$	USA,Whs	2N6324..25
2N2133	Si-NPN	=2N2130:200V	21b$	USA,Whs	2N6324..25
2N2134	Si-NPN	=2N2130:250V	21b$	USA,Whs	2N6324..25
2N2135	Si-NPN	=2N2130:300V	21b$	USA,Whs	2N6324..25
2N2136	Si-NPN	=2N2130:350V	21b$	USA,Whs	2N6324..25
2N2137(A)	Ge-PNP	AF,Sw-Pow,30V,3A,70W,B>30	23a$	USA,Mot	AL102..103,AUY19..20,2N1529..48..
2N2138(A)	Ge-PNP	=2N2137:45V	23a$	USA,Mot	AL102..103,AUY19..20,2N1545..48..
2N2139(A)	Ge-PNP	=2N2137:60V	23a$	USA,Mot	AL102..103,AUY19..20,2N1545..48..
2N214(A)	Ge-NPN	AF,40V,0,1A,0,18W	?1a	Csr,Etc	(AC127)
2N2140(A)	Ge-PNP	=2N2137:75V	23a$	USA,Mot	AL102..103,AUY19..20,2N1546..48..
2N2141(A)	Ge-PNP	=2N2137:90V	23a$	USA,Mot	AL102..103,AUY28,2N1547..48..
2N2142(A)	Ge-PNP	AF,Sw-Pow,30V,3A,70W,B>50	23a$	USA,Mot	AL102..103,AUY19..20,2N1529..48..
2N2143(A)	Ge-PNP	=2N2142:45V	23a$	USA,Mot	AL102..103,AUY19..20,2N1545..48..
2N2144(A)	Ge-PNP	=2N2142:60V	23a$	USA,Mot	AL102..103,AUY19..20,2N1545..48..
2N2145(A)	Ge-PNP	=2N2142:75V	23a$	USA,Mot	AL102..103,AUY19..20,2N1546..48..
2N2146(A)	Ge-PNP	=2N2142:90V	23a$	USA,Mot	AL102..103,AUY28,2N1547..48..
2N2147	Ge-PNP	AF-Pow,75V,5A,12,5W(Tc=81°)	23a$	RCA	AL102..103,AUY22,2N3617..18..
2N2148	Ge-PNP	60V,5A,12.5W	23a$	USA,Rca	AL102..103,AUY22,2N3617..18..
2N2149	Si-NPN	100V,2A,12W,800KHz	12a	Nec	-
2N215	Ge-PNP	AF,30V,0,03A,0,15W,0,7MHz	2a	USA	AC125..126,AC151
2N2150	Si-NPN	Sw,Pow,125V,2A,30W(Tc=100°),B>20	?49a$	USA,Tix	2N5284..85
2N2151	Si-NPN	=2N2150:B>40	?49a$	USA,Tix	2N5284..85
2N2152(A)	Ge-PNP	AF,Sw-Pow,45V,30A,170W,B>50	38a$	USA,Mot	-
2N2153(A)	Ge-PNP	=2N2152:60V	38a$	USA,Mot	-
2N2154(A)	Ge-PNP	=2N2152:75V	38a$	USA,Mot	-
2N2155(A)	Ge-PNP	=2N2152:90V	38a$	USA,Mot	-
2N2156(A)	Ge-PNP	AF,Sw-Pow,45V,30A,170W,B>80	38a$	USA,Mot	-
2N2157(A)	Ge-PNP	=2N2156:60V	38a$	USA,Mot	-
2N2158(A)	Ge-PNP	=2N2156:75V	38a$	USA,Mot	-
2N2159(A)	Ge-PNP	=2N2156:90V	38a$	USA,Mot	-
2N216	Ge-NPN	AF/HF,18V,0,05A,0,05W,3MHz	?1a	Csr,Etc	ASY28..29,ASY73..75,(AC127)
2N2160	UJT-P	=2N1671A	5r,2p	Gen,Ssc,Tix	-
2N2161	Si-NPN	AF,Sw,55V,0,05A,0,2W,<350/700nS	2a	Gen	BC167,BC182,BC237,BC547..
2N2162	Si-PNP	Chopper,30/-/30V,0,15W	2a$	USA	2N2946
2N2163	Si-PNP	Chopper,15/-/15V,0,15W	2a$	USA	2N2946
2N2164	Si-PNP	Chopper,12/-/12V,0,15W	2a$	USA	2N2946
2N2165	Si-PNP	Chopper,30V50mA0.15W18MHz	2a$	USA	2N2946
2N2166	Si-PNP	Chopper,15V50mA0.15W10MHz	2a$	USA	2N2946
2N2167	Si-PNP	Chopper,12/-/12V,0,15W	2a$	USA	2N2946
2N2168	Ge-PNP	Sw,20V,0,1A,0,06W,450MHz	2a	USA	(2N2635,2N2955..57)
2N2169	Ge-PNP	Sw,15V,0,1A,0,06W,450MHz	2a	USA	(2N705,2N964(A),2N2635,2N2955..57)
2N217	Ge-PNP	AF,35V,Ueb=12V,0,15A,0,165W	2a	USA	AC125..126,AC151
2N2170	Ge-PNP	Sw,15V,0,1A,0,06W,350MHz	2a	USA	(2N705,2N964(A),2N2635,2N2955..57)
2N2171	Ge-PNP	AF,Sw,50V,0,4A,0,225W,7,5MHz	2a$	USA,Mot	ASY77,2N1189..90
2N2172	Ge-PNP	AF,Sw,20V,0,4A,0,2W,>5MHz	2a	USA	AC128,AC152..153,ASY77,2N1189..90
2N2173	Ge-PNP	AF,Sw,25V,0,75A,0,24W	2a$	Spr	AC128,AC153
2N2174	Si-PNP	AF,Sw,45V,0,4W,1MHz	-	Nsc	BC212,BC257,BC307,BC557..
2N2175	Si-PNP	GenP,sym,6/6/6V,0,05A,0,1W,>10MHz	2a	USA	(BC213,BC258,BC308,BC558,..)

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2N2176	Si-PNP	GenP,sym,6/6/6V,0,05A,0,1W,>10MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N2177	Si-PNP	GenP,sym,6/6/6V,0,05A,0,1W,>8MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N2178	Si-PNP	GenP,sym,6/6/6V,0,05A,0,1W,>8MHz	2a	USA	(BC213,BC258,BC308,BC558,..)
2N218	Ge-PNP	HF/Sw,16V,15mA,0,035W,13MHz	2a	Csr,Etc	AF124..127,AF200
2N2180	Ge-PNP	HF/Sw,15/6/15V,0,05A,0,05W,>60MHz	37d	Phc	-
2N2181	Si-PNP	Chopper,25/25/25V,0,05A,0,15W	2a	Phc,Ray	2N2946
2N2182	Si-PNP	=2x2N2181gep	2a	Phc,Ray	2X2N2946
2N2183	Si-PNP	Chopper,15/10/15V,0,05A,0,15W	2a	Phc,Ray	2N2946
2N2184	Si-PNP	=2x2N2183gep	2a	Phc,Ray	2X2N2946
2N2185	Si-PNP	Chopper,30/30/30V,0,05A,0,15W	2a	Sem,Tdy	2N2946
2N2186	Si-PNP	=2x2N2185gep	2a	Sem,Tdy	2X2N2946
2N2187	Si-PNP	=2x2N2185gep	2a	Sem,Tdy	2X2N2946
2N2188	Ge-PNP	HF,40V,0,03A,0,125W,>60MHz	2a	USA,Tix	AF124..125,AF200
2N2189	Ge-PNP	=2N2188:>102MHz	2a	USA,Tix	AF106,AF109R,AF306
2N219	Ge-PNP	HF/Sw,16V,15mA,0,08W,10MHz	4g	Csr,Etc	AF124..127,AF200
2N2190	Ge-PNP	=2N2188:60V	2a	USA,Tix	(AF124..125,AF200)
2N2191	Ge-PNP	=2N2188:60V,>102MHz	2a	USA,Tix	(AF106,AF109R,AF306)
2N2192(A,B)	Si-NPN	AF,Sw,60V,1A,0,8W,>50MHz	2a$	USA,EUR	BC140..141,BSW27..28,2N3252..53..
2N2193(A,AS,B)	Si-NPN	AF,Sw,80V,1A,0,8W,>50MHz	2a$	USA,EUR	BC140..141,BSW39,2N3444
2N2194(A,B)	Si-NPN	AF,Sw,60V,1A,0,8W,>50MHz	2a$	USA,EUR	BC140..141,BSW27..28,2N3252..53..
2N2195(A,B)	Si-NPN	AF,Sw,45V,1A,0,6W,>50MHz	2a$	USA,EUR	BC140..141,BSW27..28,2N3252..53..
2N2196	Si-NPN	AF,Sw-Pow,80V,1A,15W,B>30	43a$	USA,Tho	(BD139,BD230,BD387,BD829,..)
2N2197	Si-NPN	=2N2196:B>75	43a$	USA,Tho	(BD139,BD230,BD387,BD829,..)
2N2198	Si-NPN	AF,80V,0,2A,0,6W,>4MHz	2a$	Cen,Etc	BC140..141,BC300..302,2N3053..
2N2199	Ge-PNP	HF,15V,0,1A,0,075W,>120MHz	2a	USA	AFY18,2N3323..25
2N22	Ge-PNP	AF,Sw,100V,Ueb=40V,0,02A,0,12W	-	Wes	(ACY39,2N2042..43)
2N220	Ge-PNP	AF,10V,2mA,0,02W,0,85MHz	2a	Csr,Etc	(AC125..126,AC151)
2N2200	Ge-PNP	HF,15V,0,1A,0,075W,>120MHz	2a	USA	AFY18,2N3323..25
2N2201	Si-NPN	AF,Sw,120V,1A,>10MHz	43a$	USA	(BD524,2SC2690,2SC3421,2SD1381..82)
2N2202	Si-NPN	=2N2201:	2a	USA	(BD524,2SC2690,2SC3421,2SD1381..82)
2N2203	Si-NPN	=2N2201:	5g	USA	(BD524,2SC2690,2SC3421,2SD1381..82)
2N2204	Si-NPN	=2N2201:	-	USA	(BD524,2SC2690,2SC3421,2SD1381..82)
2N2205	Si-NPN	Sw,25V,0,2A,0,3W,35/60nS,B>20	2a$	USA,Sgs	BSS11..12,BSX19..20,2N2368..69(A),..
2N2206	Si-NPN	=2N2205:B>40	2a$	USA,Mot	BSS11..12,BSX19..20,2N2368..69(A),..
2N2207	Ge-PNP	HF,70V,0,05A,0,26W,>140MHz	1g	USA,Phi	(AF118)
2N2208	Ge-PNP	HF,30V,10mA,0,12W	4e	USA	AF124..126,AF200
2N2209	Ge-PNP	AF,Sw,30V,0,1A,0,15W,>6MHz	2a	Cen,Stc	ASY26,ASY76..77
2N2210	Ge-PNP	AF,Sw-Pow,100V,15A,70W	38a$	USA	2N2493
2N2211	Ge-PNP	AF,Sw-Pow,80V,5A,90W	23a$	Cen,Sty	AL102..103,AUY28,2N1546..48..
2N2212	Ge-PNP	Sw,Pow,120V,10A,102W	23a$	USA,Mot	AL100,AUY38,2N2290,2N2293,2N2527
2N2213	UJT-P	40V,0,45W,Rbb<9,1kΩ	-	Gen	-
2N2214	Si-NPN	Sw,25V,0,2A,0,25W,200MHz	24b	Trw	BC238,BC548,BSW41,2N706A,2N708,..
2N2216	Si-PNP	AF,Sw,150V,0,25A,0,8W,40MHz	2a$	old	2N3636..37,2N5415,2SA712
2N2217	Si-NPN	GenP,60V,0,8A,0,8W,>250MHz,B>20	2a$	USA,Mic,Tix	BSW51..54,BSX59..61,2N3444..
2N2217A	Si-NPN	=2N2217:75V	2a$	-	BSW51..54,BSX59..61,2N3444..
2N2218(A)	Si-NPN	=2N2217:B>40	2a$	USA,EUR,Mic	BSW51..54,BSX59..61,2N3444..
2N2219(A)	Si-NPN	=2N2217:B>100	2a$	USA,EUR,Mic	BSW51..54,BSX59..61,2N3444..
2N2219A	Si-NPN	40V,0.8A,0.8W250MHz	-		-
2N222	Ge-PNP	GenP,12V,0,07W	-	Gie	-
2N2220(A)	Si-NPN	=2N2217:0,5W	2a$	USA,Mic,Tix	BSS40..41,BSW61..64,2N4014..
2N2221(A)	Si-NPN	=2N2217:0,5W,B>40	2a$	USA,EUR,Mic	BSS40..41,BSW61..64,2N4014..
2N2222	Si-NPN	-	46	Nsc	→2N2222
2N2223	Si-NPN	Dual,100V,0,5A,0,6W,>50MHz	81bs	USA,Fer,Gen	BFX70..72,2N2060
2N2223A	Si-NPN	Dual,100V,0.5A,0.6W>50MHz	81bs	USA,Fer,Gen	BFX70..72,2N2060
2N2224	Si-NPN	Sw,65V,0,5A,0,8W,>250MHz	2a$	USA,Mot	BC140..141,BC300..302,2N2218..19A,..
2N2225	Ge-PNP	Sw,15V,0,4A,0,2W,<100/200nS	2a	Cen,Stc	-
2N2226	Si-NPN	Sw,Pow,50V,10A,150W,B>100	-	USA,Whs	-
2N2227	Si-NPN	=2N2226:100V	-	USA,Whs	-
2N2228	Si-NPN	=2N2226:150V	-	USA,Whs	-
2N2229	Si-NPN	=2N2226:200V	-	USA,Whs	-
2N223	Ge-PNP	AF,-/18V,0,15A,0,25W,0,6MHz	37e	Csr,Etc	AC125..126,AC151
2N2230	Si-NPN	Sw,Pow,50V,10A,150W,B>350	-	USA,Whs	-
2N2231	Si-NPN	=2N2230:100V	-	USA,Whs	-
2N2232	Si-NPN	=2N2230:150V	-	USA,Whs	-

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2N2233	Si-NPN	=2N2230:200V	-	USA,Whs	-
2N2234	Si-NPN	AF,Sw-Pow,40V,0,5A,10W(Tc=50°),>50MHz	23a$	Itt,Sty	-
2N2235	Si-NPN	=2N2234:>100MHz	23a$	Itt,Sty	-
2N2236	Si-NPN	AF,Sw,40V,0,5A,0,6W,>50MHz	2a$	USA	BC140..141,BC300..302,2N2218..19..
2N2237	Si-NPN	=2N2236:>100MHz	2a$	USA	BC140..141,BC300..302,2N2218..19..
2N2238	Ge-PNP	HF,30V,0,05A,0,3W,>400MHz	2a	Cen	AF139,AF239(S),2N3283..86
2N2239	Si-NPN	AF-Dr/Out,60V,0,5A,2,5MHz	43a$	Sca,Ssi	(BD137,BD167,BD517,BD827,..)
2N224	Ge-PNP	AF,Sw,25V,0,15A,0,25W,0,51MHz	37e	Csr,Etc	AC125..126,AC151..152
2N2240	Si-NPN	AF,Sw,25V,0,5A,0,6W,>50MHz,B>40	2a$	USA	BC140..141,BC300..302,2N3053..
2N2241	Si-NPN	=2N2240:B>100	2a$	USA	BC140..141,BC300..302,2N3053..
2N2242	Si-NPN	Sw,40V,0,225A,,0,36W,<30/50nS	2a$	USA,Fch,Mot	BSS10..11,BSX19..20,2N2368..69(A),..
2N2243(A)	Si-NPN	AF,Sw,120V,1A,0,8W,>50MHz	2a$	USA,Mic,Tix	BC300,2N1893(A),2N2102,2N2405..
2N2244	Si-NPN	GenP,20V,0,1A,0,5W,>60MHz,B>5	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2245	Si-NPN	=2N2244:B>10	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2246	Si-NPN	=2N2244:B>20	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2247	Si-NPN	GenP,45V,0,1A,0,5W,>60MHz,B>5	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N2248	Si-NPN	=2N2247:B>10	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N2249	Si-NPN	=2N2247:B>20	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N225	Ge-PNP	=2x2N224gep	37e	Csr,Etc	AC125..126,AC151..152
2N2250	Si-NPN	GenP,25V,0,1A,0,5W,>60MHz,B>5	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2251	Si-NPN	=2N2250:B>10	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2252	Si-NPN	=2N2250:B>20	2a$	Nsc,Sty	BC168,BC183,BC238,BC548..
2N2253	Si-NPN	GenP,50V,0,1A,0,5W,>60MHz,B>5	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N2254	Si-NPN	=2N2253:B>10	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N2255	Si-NPN	=2N2253:B>20	2a$	Nsc,Sty	BC167,BC182,BC237,BC547..
2N2256	Si-NPN	Fast-Sw,7V,0,1A,0,3W,<7/7nS,B>20	2a$	USA,Mot	-
2N2257	Si-NPN	=2N2256:B>40	2a$	USA,Mot	-
2N2258	Ge-PNP	Fast-Sw,7V,0,1A,0,15W,<7/7nS,B>20	2a$	USA,Mot	-
2N2259	Ge-PNP	=2N2258:B>40	2a$	USA,Mot	-
2N226	Ge-PNP	AF,Sw,30V,0,15A,0,25W,0,4MHz	37e	Csr,Etc	AC125..126,AC151..152
2N2260	Thy-GTO	30V,0,2A,Igt<0,25mA	-		-
2N2261	Thy-GTO	=2N2260:Igt<0,5mA	-		-
2N2262	Thy-GTO	=2N2260:Igt<5mA	-		-
2N2266	Ge-PNP	Sw,Pow,80V,5A,50W	?37b$	USA	-
2N2267	Ge-PNP	=2N2266:100V	?37b$	USA	-
2N2268	Ge-PNP	=2N2266:Iso	?37b	USA	-
2N2269	Ge-PNP	=2N2267:Iso	?37b	USA	-
2N227	Ge-PNP	=2x2N226gep	37e	Csr,Etc	AC125..126,AC151..152
2N2270(L,S)	Si-NPN	AF,Sw,60V,1A,1W,250MHz	2a$	USA,EUR	BC140..141,2N1990,2N2218..19(A)..
2N2271	Ge-PNP	AF,Sw,20V,0,5A,0,25W	2a&	USA	AC128,AC152..153,AC188,2SB405
2N2272	Si-NPN	Sw,40V,0,5A,0,36W,<40/40nS	2a$	Cen,Sty	BSS10,BSX26,BSX39,2N4013..14
2N2273	Ge-PNP	HF,25V,0,1A,0,15W,>250MHz	2a$	USA,Mot	AFY18,2N3323..25,(AF106,AF109R)
2N2274	Si-PNP	Chopper,25/25/25V,0,05A,0,15W	2a	USA	2N2946
2N2275	Si-PNP	=2x2N2274gep	2a	USA	2X2N2946
2N2276	Si-PNP	Chopper,15/10/10V,0,05A,0,15W	2a	USA	2N2945
2N2277	Si-PNP	=2x2N2276gep	2a	USA	2X2N2945
2N2278	Si-PNP	Chopper,15/15/15V,0,05A,0,15W	2a	USA	2N2945
2N2279	Si-PNP	=2x2N2278gep	2a	USA	2X2N2945
2N228	Ge-NPN	AF,Sw,40V,0,1A,0,18W,0,6MHz	?1a	Csr,Etc	(AC127)
2N2280	Si-PNP	Chopper,10/6/10V,0,05A,0,15W	2a	USA	2N2944
2N2281	Si-PNP	=2x2N228gep	2a	USA	2X2N2944
2N2282	Ge-PNP	Sw,Pow,60V,3A,5W,>20MHz	43a$	USA	-
2N2283	Ge-PNP	=2N2282:100V	43a$	USA	-
2N2284	Ge-PNP	=2N2282:200V	43a$	USA	-
2N2285	Ge-PNP	AF,Sw-Pow,60V,25A,106W	23a$	USA,Mot	2N1651..53
2N2286	Ge-PNP	=2N2285:100V	23a$	USA,Mot	2N1652..53
2N2287	Ge-PNP	=2N2285:120V	23a$	USA,Mot	2N1653
2N2288	Ge-PNP	AF,Sw-Pow,40V,10A,70W,B>20	23a$	USA,Mot	AL100..101,AUY21,2N1549..1560..
2N2289	Ge-PNP	=2N2288:80V	23a$	USA,Mot	AL100..101,AUY37,2N1559..1560..
2N229	Ge-NPN	AF,Sw,10V,Ueb=20V,0,1A,0,18W	?1a	Csr,Etc	(AC127,ASY28..29,ASY73..75)
2N2290	Ge-PNP	=2N2288:120V	23a$	USA,Mot	AL100,AUY38,2N2527..28
2N2291	Ge-PNP	AF,Sw-Pow,40V,10A,70W,B>50	23a$	USA,Mot	AL100..101,AUY21,2N1549..1560..
2N2292	Ge-PNP	=2N2291:80V	23a$	USA,Mot	AL100..101,AUY37,2N1559..1560..
2N2293	Ge-PNP	=2N2291:120V	23a$	USA,Mot	AL100,AUY38,2N2527..28

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2N2294	Ge-PNP	AF,Sw-Pow,40V,10A,60W	23a$	USA	AL100..101,AUY21,2N2288..93..
2N2295	Ge-PNP	=2N2294:80V	23a$	USA	AL100..101,AUY37,2N2292..93..
2N2296	Ge-PNP	=2N2294:120V	23a$	USA	AL100,AUY38,2N2293,2N2527..28
2N2297(S)	Si-NPN	GenP,80V,1A,0,8W,10MHz	2a$	USA,EUR	BC140..141,BSX45..47,2N1990..
2N23	Ge-PNP	AF,Sw,50V,Ueb=40V,0,04A,0,08W	-	Wes	(ACY39,ASY48,ASY77,2N2042..43)
2N230	Ge-PNP	AF-Pow,60V,Ueb=30V,2A,15W	2a$	Mal	AUY18,AUY35..36
2N2303	Si-PNP	AF,Sw,50V,0,5A,0,6W,>60MHz	2a$	USA,EUR	BC161,BC303..304,BC361,2SA606..
2N2304	Si-NPN	AF,Sw-Pow,60V,3A,25W	2a$	USA	(BD241A,BD535,BD539A,BD935,..)
2N2305	Si-NPN	AF,Sw-Pow,60V,6A,75W	23a$	USA	BD245A,BDV91,BDX91,2N4914..15..
2N2306	Si-NPN	Sw,Pow,75V,2A,13W,>175MHz	2a$	Trw	(BD139,BD230,BD379,2SD1177..78,..)
2N2307	UJT-P	0,25W,Ip<2µA,Rbb<9,1kΩ	-	Inr	-
2N2308	Si-NPN	Sw,Pow,100V,3A,25W,>1MHz	2a$	USA	(BD241C,BD539C,BD937,2SD712,..)
2N2309	Si-NPN	GenP,30V,0,6A,40MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N231	Ge-PNP	HF,4,5V,3mA,9mW,20MHz	37d	Csr	AF124..127,AF200
2N2310	Si-NPN	GenP,60V,0,5A,0,35W,40MHz,B>12	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2311	Si-NPN	=2N2310:100V	2a$	USA	BC639,BCX24,2N3700..01,2SD667..
2N2312	Si-NPN	GenP,60V,0,5A,0,35W,40MHz,B>30	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2313	Si-NPN	=2N2312:100V	2a$	USA	BC639,BCX24,2N3700..01,2SD667..
2N2314	Si-NPN	GenP,60V,0,5A,0,35W,>40MHz,B>20	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2315	Si-NPN	GenP,60V,0,5A,0,35W,>50MHz,B>40	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2316	Si-NPN	GenP,120V,0,5A,0,35W,>50MHz,B>40	2a$	USA	BCX22,2N3700..01,2SC2235,2SD667..
2N2317	Si-NPN	GenP,75V,0,5A,0,35W,>60MHz,B>40	2a$	USA	BC639,BCX24,2N3700..01,2SD667..
2N2318	Si-NPN	Sw,30V,0,2A,0,36W,45/40nS	2a$	USA	BSS11..12,BSX19..20,2N2368..69(A),..
2N2319	Si-NPN	=2N2318:0,3W	2a$	USA,Mot	BSS11..12,BSX19..20,2N2368..69(A),..
2N232	Ge-PNP	HF,4,5V,3mA,9mW,30MHz	37d	Csr,Sty	AF124..127,AF200
2N2320	Si-NPN	=2N2318:0,6W	2a$	USA	BSS28..29,BSV69,2N3724(A),2SC1385..
2N2322	Thy-50Hz	25V,1A(Tc=85°),Igt/Ih<0,2/<2mA	2a$	USA,Mot,Tix	2N6332,TAG615-100,(MCR606-2)
2N2322A	Thy-50Hz	=2N2322:Igt/Ih<0,02/<2mA	2a$	-	-
2N2323	Thy-50Hz	=2N2322:50V	2a$	-	2N6333,TAG615-100,(MCR606-2)
2N2323A	Thy-50Hz	=2N2323:Igt/Ih<0,02/<2mA	2a$	-	-
2N2324	Thy-50Hz	=2N2322:100V	2a$	-	2N6334,TAG615-100,(MCR606-3)
2N2324A	Thy-50Hz	=2N2324:Igt/Ih<0,02/<2mA	2a$	-	-
2N2325	Thy-50Hz	=2N2322:150V	2a$	-	2N6335,TAG615-200,(MCR606-4)
2N2325A	Thy-50Hz	=2N2325:Igt/Ih<0,02/<2mA	2a$	-	-
2N2326	Thy-50Hz	=2N2322:200V	2a$	-	2N6335,TAG615-200,(MCR606-4)
2N2326A	Thy-50Hz	=2N2326:Igt/Ih<0,02/<2mA	2a$	-	-
2N2327	Thy-50Hz	=2N2322:250V	2a$	-	2N6336,TAG615-300,(MCR606-5)
2N2327A	Thy-50Hz	=2N2327:Igt/Ih<0,02/<2mA	2a$	-	-
2N2328	Thy-50Hz	=2N2322:300V	2a$	-	2N6336,TAG615-300,(MCR606-5)
2N2328A	Thy-50Hz	=2N2328:Igt/Ih<0,02/<2mA	2a$	-	-
2N2329	Thy-50Hz	=2N2322:400V	2a$	-	2N6337,TAG615-400,(MCR606-6)
2N2329A	Thy-50Hz	=2N2329:Igt/Ih<0,02/<2mA	2a$	-	-
2N233	Ge-NPN	HF,10V,0,1A,0,15W,>2MHz	?1a	Csr,Etc	AC127,ASY28..29,ASY73..75
2N2330(S)	Si-NPN	Chopper,30V,0,5A,0,8W,>100MHz	2a$	USA,Mot	-
2N2331(S)	Si-NPN	=2N2330:0,5W	2a$	USA,Mot	-
2N2332	Si-PNP	Chopper,15/5/15V,0,1A,0,15W	2a	USA	2N2944
2N2333	Si-PNP	Chopper,15/5/15V,0,1A,0,15W	2a	USA	2N2944
2N2334	Si-PNP	Chopper,30/15/30V,0,1A,0,15W	2a	USA	2N2946
2N2335	Si-PNP	Chopper,30/15/30V,0,1A,0,15W	2a	USA	2N2946
2N2336	Si-PNP	Chopper,50/35/50V,0,1A,0,15W	2a	USA	2N2946
2N2337	Si-PNP	Chopper,50/35/50V,0,1A,0,15W	2a	USA	2N2946
2N2338	Si-NPN	Sw,Pow,60V,7,5A,150W	38a$	Cen,Ssi	-
2N2339	Si-NPN	Sw,Pow,60V,2,5A,40W	-	USA	-
2N233A	Ge-NPN	=2N233:18V	?1a	-	AC127,ASY28..29,ASY73..75
2N234(A)	Ge-PNP	AF-Pow,30V,3A,25W	23a$	USA	AD149,AUY19..20,2N2137..2146..
2N2340	Si-NPN	AF-Pow,50V,1A,15W,B>10	43a$	Del	(BD137,BD167,BD228,BD235,..)
2N2341	Si-NPN	AF-Pow,50V,1A,15W,B>40	43a$	Del	(BD137,BD167,BD228,BD235,..)
2N2342	Si-NPN	=2N2340:100V	43a$	Del	(BD139,BD169,BD230,BD237,..)
2N2343	Si-NPN	=2N2341:100V	43a$	Del	(BD139,BD169,BD230,BD237,..)
2N2344	Thy-50Hz	25V,1A(Tc=55°),Igt/Ih<0,02/<1mA	2a$	Gen,Mot,Tag	2N2322A
2N2345	Thy-50Hz	=2N2344:50V	2a$	-	2N2323A
2N2346	Thy-50Hz	=2N2344:100V	2a$	-	2N2324A
2N2347	Thy-50Hz	=2N2344:150V	2a$	-	2N2325A
2N2348	Thy-50Hz	=2N2344:200V	2a$	-	2N2326A

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2N2349	Si-NPN	HF,40V,0,025A,0,15W	2a$	USA	BF198..199,BF224..225,BF596..597,..
2N2235(A,B)	Ge-PNP	AF-Pow,50V,3A,25W	23a$	USA	AD149,AUY19..20,2N2144..2146..
2N2350(A)	Si-NPN	GenP,60V,1A,0,4W,>50MHz	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2351(A)	Si-NPN	GenP,80V,1A,0,4W,>50MHz	2a$	USA	BC639,BCX24,2N3700..01,2SD667..
2N2352(A)	Si-NPN	GenP,60V,1A,0,4W,>50MHz	2a$	USA	BC337A,BC637,BC639,2SD667..
2N2353(A)	Si-NPN	GenP,45V,1A,0,4W,>50MHz	2a$	USA	BC337(A),BC635,BC637,BC639..
2N2354	Ge-NPN	AF,20V,0,15A,0,18W	?1a	Ssi	AC127,ASY28..29,ASY73..75
2N2356(A)	Si-NPN	Dual,Chopper,25V,0,5A,0,6W	81bv	USA,Gen,Tho	-
2N2357	Ge-PNP	Sw,Pow,60V,50A,170W	23a$	USA,Mot	2N4280..83,2N5435..40
2N2358	Ge-PNP	=2N2357:100V	23a$	USA,Mot	2N5436,2N5439
2N2359	Ge-PNP	=2N2357:120V	23a$	USA,Mot	2N5437,2N5440
2N2236(A,B)	Ge-PNP	AF-Pow,50V,3A,25W	23a$	USA	AD149,AUY19..20,2N2144..2146..
2N2360	Ge-PNP	VHF,20V,0,05A,0,06W	5g	Spr	AF139,AF239(S),2N3283..86
2N2361	Ge-PNP	VHF,20V,0,05A,0,06W	5g	Spr	AF139,AF239(S),2N3283..86
2N2362	Ge-PNP	VHF,20V,0,05A,0,06W	5g	Spr	AF139,AF239(S),2N3283..86
2N2363	Ge-PNP	VHF,30V,0,05A,0,075W	5g	Idi	AF139,AF239(S),2N3283..86
2N2364(A)	Si-NPN	GenP,120V,1A,0,4W,>50MHz	2a$	USA	BCX22,2N3700..01,2SC2235,2SD667..
2N2368	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<12/15nS,B>20	2a$	USA,EUR,Mic	BSS10..11,BSX19..20,2N3261,2SC2901
2N2369(A)	Si-NPN	=2N2368:B>40	2a$	USA,EUR,Mic	BSS10..11,BSX19..20,2N3261,2SC2901
2N2369A	Si-NPN	40V,0.2A,36W 12/18nS	-		-
2N237	Ge-PNP	AF,45V,0,02A,0,15W,0,5MHz	?1a	Csr,Etc	2SB56A
2N2370	Si-PNP	Chopper,15/15/15V,0,05A,0,2W	2a	USA	2N2945
2N2371	Si-PNP	Chopper,15/15/15V,0,05A,0,2W	2a	USA	2N2945
2N2372	Si-PNP	=2N2370:0,15W	2a	USA	2N2945
2N2373	Si-PNP	=2N2371:0,15W	2a$	USA	2N2945
2N2374	Ge-PNP	AF-Driver,35/35/35V,0,5A,0,25W,15MHz	2a	USA	(ASY76..77)
2N2375	Ge-PNP	AF-Driver,35/35/35V,0,5A,0,25W,9MHz	2a	USA	(ASY76..77)
2N2376	Ge-PNP	=2N2375:gep	2a	USA	(ASY76..77)
2N2377	Si-PNP	HF/Sw,25V,0,05A,0,15W,>8MHz	2a	USA	BC213,BC258,BC308,BC558..
2N2378	Si-PNP	HF/Sw,10V,0,05A,0,15W,>8MHz	2a	USA	BC213,BC258,BC308,BC558..
2N2379	Ge-PNP	Sw,Pow,100V,15A,150W	38a$	oid	2N2493
2N238	Ge-PNP	AF,20V,0,15A,0,05W,>1,3MHz	?1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2380(A)	Si-NPN	AF,Sw,80V,0,5A,0,6W,>100MHz	2a$	USA	BC140..141,BC300..301,2N2218..19A,..
2N2381	Ge-PNP	Sw,30V,0,5A,0,3W,>300MHz	2a$	Mot,Sty	-
2N2382	Ge-PNP	=2N2381:45V	2a$	Mot,Sty	-
2N2383	Si-NPN	AF,Sw-Pow,80V,2A,85W	-	USA	2N1722..23,(BD243B,BD539B,BD951..)
2N2384	Si-NPN	AF,Sw-Pow,80V,5A,85W	49m	USA	2N3487..92,(BD243B,BD539B,BD951..)
2N2386(A)	P-FET	GenP,20V,Idss=0,9..15mA,Up<8V	2a&	Sol,Tix	2N2497..2500
2N2387	Si-NPN	AF,LN,45V,0,03A,0,3W,>30MHz,B>40	24b	TI	BC382..384,BC413..414,BC550..
2N2388	Si-NPN	=2N2387:B>100	24b	TI	BC382..384,BC413..414,BC550..
2N2389	Si-NPN	AF,Sw,75V,0,5A,0,45W,>60MHz,B>40	24b	TI	BC639,2SD667,2SD774,2SD1226..
2N2390	Si-NPN	=2N2389:>70MHz,B>100	24b	TI	BC639,2SD667,2SD774,2SD1226..
2N2391	Si-PNP	GenP,25V,0,05A,0,3W,100MHz,B>15	24b	TI	BC213,BC258,BC308,BC558..
2N2392	Si-PNP	=2N2391:B>30	24b	TI	BC213,BC258,BC308,BC558..
2N2393	Si-PNP	GenP,50V,0,3A,0,45W,>50MHz,B>20	24b	TI	BC327(A),BC638,BC640,2SB647..
2N2394	Si-PNP	=2N2393:>60MHz,B>30	24b	TI	BC327(A),BC638,BC640,2SB647..
2N2395	Si-NPN	AF,Sw,60V,0,3A,0,45W,>40MHz,B>20	24b	TI	BC337A,BC637,BC639,2SD667..
2N2396	Si-NPN	=2N2395:>50MHz,B>40	24b	TI	BC337A,BC637,BC639,2SD667..
2N2397	Si-NPN	Sw,35V,0,2A,0,3W,<40/70nS	24b	Syl	BSS10..11,BSX19..20,2N2368..69(A),..
2N2398	Ge-PNP	VHF/UHF,20V,0,05A,0,06W	5g	Sem,Spr	AF139,AF239(S),2N3283..86
2N2399	Ge-PNP	VHF/UHF,20V,0,05A,0,06W	5g	Sem,Spr	AF139,AF239(S),2N3283..86
2N24	Ge-PNP	AF,Sw,30V,0,025A,0,12W	-	Wes	(ACY39,ASY48,ASY77,2N2042..43)
2N240	Ge-PNP	HF,6V,15mA,0,03W,>30MHz	37d	USA	AF124..127,AF200
2N2400	Ge-PNP	Sw,12V,0,1A,0,15W,>150MHz	2a	USA	2N960..967,2N2635,2N2955..57
2N2401	Ge-PNP	Sw,15V,0,1A,0,15W,>200MHz	2a	USA	2N705(A),2N964(A),2N2635,2N2955..57
2N2402	Ge-PNP	Sw,18V,0,1A,0,15W,>250MHz	2a	USA	2N2635,2N2955..57
2N2403	Si-NPN	Sw,60V,1A,150MHz,B>20	2a$	Nsc	BSW27..28,BSX59..61,2N3252..53..
2N2404	Si-NPN	=2N2403:B>40	2a$	Nsc	BSW27..28,BSX59..61,2N3252..53..
2N2405(L,S)	Si-NPN	AF,Sw,140V,1A,1W,>120MHz	2a$	USA,EUR	2N2102,2N3019..3020
2N241(A)	Ge-PNP	AF,25V,0,2A,0,1(A:0,2)W,1,3MHz	1a&	USA	AC125..126,AC151,2SB54,2SB56
2N2410	Si-NPN	Sw,60V,0,8A,0,8W,35/40nS	2a$	USA,EUR	BSS27,BSV77,BSV95,2N5189..
2N2410/S1	Si-NPN	=2N2410:0,3W	24b	Syl	BSS27,BSV77,BSV95,2N5189..
2N2411	Si-PNP	Sw,25V,0,1A,0,3W,15/74nS,B>20	2a$	USA,Phi,Tix	BSX36
2N2412	Si-PNP	=2N2411:B>40	2a$	USA,Phi,Tix	BSX36

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2N2413	Si-NPN	HF/Sw,40V,0,2A,0,3W,>300MHz	2a$	Sty,Tix	BSS10..11,BSX19..20,2N2368..69(A),..
2N2414	Si-NPN	Dual,60V,0,5A,0,6W,>60MHz	81bs	USA	BFX70..72,2N2060,2N2223
2N2415	Ge-PNP	VHF/UHF,15V,0,02A,0,075W,>550MHz	5g	USA,Mot,Tix	AF139,AF239(S),2N3283..86
2N2416	Ge-PNP	VHF/UHF,15V,0,02A,0,075W,>400MHz	5g	USA,Mot,Tix	AF139,AF239(S),2N3283..86
2N2417	UJT-P	=2N489:0,3W	5r	Gen	→2N489
2N2418	UJT-P	=2N490:0,3W	5r	Gen	→2N490
2N2419	UJT-P	=2N491:0,3W	5r	Gen	→2N491
2N242	Ge-PNP	AF,Sw-Pow,45,5A,106W	23a$	USA	AL102..103,AUY28,2N1539..48..
2N2420	UJT-P	=2N492:0,3W	5r	Gen	→2N492
2N2421	UJT-P	=2N493:0,3W	5r	Gen	→2N493
2N2422	UJT-P	=2N494:0,3W	5r	Gen	→2N494
2N2423	Ge-PNP	Sw,Pow,100V,5A,90W	23a$	USA	AL102..103,AUY37,2N1547..48..
2N2424	Si-PNP	AF,Sw,40V,0,05A,0,375W,<300/500nS	2a	USA	BC212,BC307,BC557,BCY77,BCY79..
2N2425	Si-PNP	AF,Sw,50V,0,05A,0,375W,<500/725nS	2a	USA	BC212,BC307,BC557,BCY77,BCY79..
2N2426	Ge-NPN	AF,Sw,40V,0,2A,0,15W,>25MHz	2a	Stc,Sty	-
2N2427	Si-NPN	GenP,40V,0,05A,0,5W,50MHz	2a$	USA	BC167,BC182,BC237,BC547..
2N2428	Ge-PNP	AF,32V,0,1A,0,165W	2a	Amp,Phc	AC125..126,AC151,2SB54,2SB56
2N2429	Ge-PNP	AF,32V,0,1A,0,165W	2a	Amp,Phc	AC125..126,AC151,2SB54,2SB56
2N243	Si-NPN	AF/HF,60V,0,06A,0,75W,a>9	?1a	USA	(BC140..141,BC300..302,BC637,..)
2N2430	Ge-NPN	AF-Driver,32V,0,5A,0,28W	2a	Amp,Phc	AC127,AC176,AC187
2N2431(MP)	Ge-PNP	AF-Driver,32V,0,5A,0,225W	2a	Amp,Phc	AC128,AC152..153,2SB324,2SB415
2N2432	Si-NPN	Chopper,30V,0,1A,0,3W,>20MHz	2a$	USA,Tix	2N4138
2N2432A	Si-NPN	=2N2432:45V	2a$	USA,Tix	2N4138
2N2433	Si-NPN	GenP,75V,1A,0,5W,>80MHz,B>40	2a$	Sca,Ssi	BC639,BCX24,2N3700..01,2SD667..
2N2434	Si-NPN	GenP,75V,1A,0,5W,>90MHz,B>100	2a$	Sca,Ssi	BC639,BCX24,2N3700..01,2SD667..
2N2435	Si-NPN	GenP,120V,0,5A,0,5W,>80MHz,B>40	2a$	Sca,Ssi	BCX22,2N3700..01,2SC2235,2SD667..
2N2436	Si-NPN	GenP,120V,0,5A,0,5W,>90MHz,B>100	2a$	Sca,Ssi	BCX22,2N3700..01,2SC2235,2SD667..
2N2437	Si-NPN	GenP,100V,0,5A,0,5W,>70MHz,B>15	2a$	Sca,Ssi	BC639,BCX24,2N3700..01,2SD667..
2N2438	Si-NPN	=2N2438:>80MHz,B>35	2a$	Sca,Ssi	BC639,BCX24,2N3700..01,2SD667..
2N2439	Si-NPN	=2N2438:>90MHz,B>75	2a$	Sca,Ssi	BC639,BCX24,2N3700..01,2SD667..
2N244	Si-NPN	=2N243:a>25	?1a	USA	(BC140..141,BC300..302,BC637,..)
2N2440	Si-NPN	AF,Sw,120V,0,5A,0,8W,>90MHz	2a$	USA	BC300,2N2102,2N2405,2N3019..3020
2N2443	Si-NPN	AF,Sw,120V,0,8W,>50MHz	2a$	USA,Fch	BC300,2N2102,2N2405,2N3019..3020
2N2444	Ge-PNP	Sw,Pow,80V,10A,85W	23a$	USA	AL100..101,AUY37,2N2292..93..
2N2445	Ge-PNP	Sw,Pow,100V,15A,90W	23a$	USA	2N1552,2N1556,2N1560
2N2446	Ge-PNP	Sw,Pow,60V,7A,90W	23a$	Cen	AL102..103,AUY22,2N3615..18..
2N2447	Ge-PNP	AF,45V,0,1A,0,075W	37b	Ray	2N1191..94,2SB56A
2N2448	Ge-PNP	AF,45V,0,1A,0,075W	-	Ray	2N1191..94,2SB56A
2N2449	Ge-PNP	AF,35V,0,1A,0,075W	37b	Ray	AC125..125,AC151,2SB54,2SB56
2N2450	Ge-PNP	AF,35V,0,1A,0,075W	-	Ray	AC125..125,AC151,2SB54,2SB56
2N2451	Ge-PNP	HF/Sw,6/5/6V,0,05A,0,025W,>80MHz	37d	Spr	-
2N2452	Opto	-	-	-	-
2N2453	Si-NPN	Dual,60V,0,05A,0,3W,>60MHz	81bs	USA,EUR,Mic	2N2060,2N2223,2N2919..20
2N2453A	Si-NPN	=2N2453:80V	81bs	-	2N2060,2N2223
2N2455	Ge-PNP	Sw,15V,0,2A,0,15W,>600MHz,<-/65nS	2a$	Ssi	-
2N2456	Ge-PNP	Sw,15V,0,2A,0,15W,>1000MHz,<-/65nS	2a$	Ssi	-
2N2457	FET	Up<5V	2	Fch	-
2N2458	FET	Up<5V	24	Fch	-
2N2459	Si-NPN	GenP,100V,0,05A,0,4W,>100MHz,a>40	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2460	Si-NPN	=2N2459:>120MHz,a>70	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2461	Si-NPN	=2N2459:>140MHz,a>115	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2462	Si-NPN	=2N2459:>160MHz,a>160	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2463	Si-NPN	GenP,100V,0,05A,0,5W,>100MHz,a>40	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2464	Si-NPN	=2N2463:>120MHz,a>70	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2465	Si-NPN	=2N2463:>140MHz,a>115	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2466	Si-NPN	=2N2463:>160MHz,a>160	2a$	USA	BSS38,BSX21,2SC2240,2SC2459..
2N2467	Ge-PNP	AF,Sw,60V,3A,>20MHz	2a$	Sol,Stc	-
2N2468	Ge-PNP	=2N2467:100V	2a$	Sol,Stc	-
2N2469	Ge-PNP	=2N2467:200V	2a$	Sol,Stc	-
2N247	Ge-PNP	HF,40V,10mA,0,08W,30MHz	1g	Rca,Syl	AF124..127,AF200
2N247/33	Ge-PNP	=2N247:0,12W	5g	Syl	AF124..127,AF200
2N2472	Si-NPN	AF,Sw,120V,1A,>10MHz	43a$	Gen,Sca	(BD524,2SC2384,2SC2481,2SD1381..82)
2N2473	Si-NPN	=2N2472:	5g	Gen	(BD524,2SC2384,2SC2481,2SD1381..82)
2N2474	Si-PNP	Chopper,30V,0,05A,0,25W	2a	USA	-

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2N2475	Si-NPN	Fast-Sw,15V,0,1A,0,3W,<20/15nS	2a$	USA,EUR	BSV89..92,BSX44,2N2368..69(A)..
2N2476	Si-NPN	Sw,60V,1A,0,6W,<25/45nS,B>40	2a$	USA,EUR	BSS27,BSV77,BSV95,2N5189..
2N2477	Si-NPN	=2N2476:B>20	2a$	USA,EUR	BSS27,BSV77,BSV95,2N5189..
2N2478	Si-NPN	AF,Sw,120V,0,5A,0,6W,>200MHz	2a$	USA	BC300,2N2102,2N2405,2N3019..20
2N2479	Si-NPN	AF,Sw,80V,0,5A,0,6W,>150MHz	2a$	USA	BC140..141,BC300..301,BSW39..
2N248	Ge-PNP	HF,25V,5mA,0,03W,50MHz	?1a	Etc,Tix	AF124..127,AF200
2N2480	Si-NPN	Dual,75V,0,5A,0,6W,>50MHz	81bs	USA,Mot	BFX70..72,2N2060,2N2223
2N2480A	Si-NPN	=2N2480:80V	81bs	-	BFX70..72,2N2060,2N2223
2N2481	Si-NPN	Sw,40V,0,36W,>300MHz,<40/55nS	2a$	USA,Mot	BSS10..11,BSX19..20,2N2368..69(A),..
2N2482	Ge-NPN	HF,20V,0,1A,0,15W,>600MHz	2a$	USA	-
2N2483	Si-NPN	AF-LN,60V,0,05A,0,36W,100MHz,B>40	2a$	USA,EUR	2N3117,2SC1775(A),2SC2240,2SC2390..
2N2484(A)	Si-NPN	=2N2483:B>100	2a$	USA,EUR	2N3117,2SC1775(A),2SC2240,2SC2390..
2N2485	Si-NPN	AF,Sw,120V,1A,8,8W(Tc=25°),>100MHz	2a$	Nsc,Sty	BUX49,BUY41,2SC1860
2N2486	Si-NPN	=2N2485:140V	2a$	Nsc,Sty	BUX49,BUY41,2SC1860
2N2487	Ge-PNP	HF/Sw,15V,0,1A,0,06W,>360MHz	2a	USA	2N3283..86
2N2488	Ge-PNP	HF/Sw,15V,0,1A,0,06W,>360MHz	2a	USA	2N3283..86
2N2489	Ge-PNP	HF/Sw,20V,0,1A,0,06W,>300MHz	2a	USA	2N3283..86
2N249	Ge-PNP	AF,25V,0,2A,0,35W	2a	Csr,Etc	AC125..126,AC151
2N2490	Ge-PNP	AF,Sw-Pow,70V,15A,170W,B>20	38a$	USA,Mot	2N1981..82,2N2075..76,2N2079..80
2N2491	Ge-PNP	AF,Sw-Pow,60V,15A,170W,B>35	38a$	USA,Mot	2N1981..82,2N2075..76,2N2079..80
2N2492	Ge-PNP	AF,Sw-Pow,80V,15A,170W,B>25	38a$	USA,Mot	2N1982,2N2075,2N2079
2N2493	Ge-PNP	AF,Sw-Pow,100V,15A,170W,B>25	38a$	USA,Mot	-
2N2494	Ge-PNP	HF,40V,10mA,0,125W,>135MHz	1g	Amp	AF106,AF109R,AF306,2N3323..25
2N2495	Ge-PNP	=2N2494:	5g	Amp	AF106,AF109R,AF306,2N3323..25
2N2496	Ge-PNP	=2N2494:0,1W	5g	Amp	AF106,AF109R,AF306,2N3323..25
2N2497	P-FET	GenP,20V,Idss>1mA,Up<5V	2a&	Sol,Tix	2N2608,2N3329,2N5460
2N2498	P-FET	GenP,20V,Idss>2mA,Up<6V	2a&	Sol,Tix	2N2609,2N3330,2N5461
2N2499	P-FET	GenP,20V,Idss>5mA,Up<8V	2a&	Sol,Tix	BF320B,2N3331,2N5462
2N25	Ge-PNP	AF,Sw,50V,0,03A,0,2W,9MHz	-	Wes	(ACY39,ASY48,ASY77,2N2042..43)
2N250	Ge-PNP	Sw,Pow,30V,3A,25W	23a$	TI	AD149,AUY10..20,2N2137..46..
2N2500	P-FET	GenP,20V,Idss>1mA,Up<6V	2a&	Sol,Tix	2N2608,2N3332,2N5460
2N2501	Si-NPN	Sw,40V,0,36W,>350MHz	2a$	USA,Mot	BSS10..11,BSX19..20,2N2368..69(A),..
2N2509	Si-NPN	GenP,125V,0,2A,0,36W,>45MHz	2a$	USA,Fch,Nsc	BFR86,2SC2240,2SC2459,2SC3245(A)
2N250A	Ge-PNP	Sw,Pow,40V,7A,90W	23a$	-	AL102..103,AUY21..22,2N3611..18..
2N251	Ge-PNP	Sw,Pow,60V,3A,25W	23a$	TI	AL102..103,AUY19..20,2N2144..46..
2N2510	Si-NPN	GenP,100V,0,2A,0,36W,>45MHz	2a$	USA,Fch,Nsc	BFR86,2SC2240,2SC2459,2SC3245(A)
2N2511	Si-NPN	GenP,80V,0,2A,0,36W,>45MHz	2a$	USA,Fch,Nsc	BC546,2SC2240,2SC2459,2SC3245(A)
2N2512	Ge-PNP	HF,70V,0,03A,0,15W,>140MHz	5g	Amp	(AF118)
2N2514	Si-NPN	GenP,80V,0,1A,0,4W,30MHz,B>15	2a$	USA,Nsc	BC546,2SC2240,2SC2459,2SC3245(A)
2N2515	Si-NPN	=2N2514:60MHz,B>30	2a$	USA,Nsc	BC546,2SC2240,2SC2459,2SC3245(A)
2N2516	Si-NPN	=2N2514:100MHz,B>60	2a$	USA,Nsc	BC546,2SC2240,2SC2459,2SC3245(A)
2N2517	Si-NPN	GenP,125V,0,05A,0,4W,30MHz,B>15	2a$	USA,Nsc	BSS38,BSX21,2SC2240,2SC2459..
2N2518	Si-NPN	=2N2517:60MHz,B>30	2a$	USA,Nsc	BSS38,BSX21,2SC2240,2SC2459..
2N2519	Si-NPN	=2N2517:100MHz,B>60	2a$	USA,Nsc	BSS38,BSX21,2SC2240,2SC2459..
2N251A	Ge-PNP	Sw,Pow,60V,7A,90W	23a$	-	AL102..103,AUY21..22,2N3614..18..
2N252	Ge-PNP	HF,-/16V,5mA,0,03W	?1a	Csr,Etc	AF124..127,AF200
2N2520	Si-NPN	GenP,60V,0,1A,0,4W,>50MHz,B>18	2a$	USA	BC174,BC182,BC190,BC546..
2N2521	Si-NPN	=2N2520:B>36	2a$	USA	BC174,BC182,BC190,BC546..
2N2522	Si-NPN	=2N2520:B>76	2a$	USA	BC174,BC182,BC190,BC546..
2N2523	Si-NPN	GenP,LN,60V,0,03A,0,4W,>70MHz,B>60	2a$	USA	2N2483..84,2N3117,2SC2240,2SC2390..
2N2524	Si-NPN	=2N2523:B>150	2a$	USA	2N2483..84,2N3117,2SC2240,2SC2390..
2N2525	Si-NPN	HF-Pow,100V,1A,16W,>56MHz	49a	USA	-
2N2526	Ge-PNP	Sw,Pow,80V,10A,85W	23a$	USA,Mot	AL100..101,2N2289..90,2N2292..93
2N2527	Ge-PNP	=2N2526:120V	23a$	USA,Mot	AL100,2N2290,2N2293
2N2528	Ge-PNP	=2N2526:160V	23a$	USA,Mot	-
2N2529	Si-NPN	GenP,45V,0,025A,0,15W,>6MHz,B>10	2a	Sty	BC167,BC182,BC237,BC547..
2N253	Ge-NPN	HF,12V,5mA,0,065W	?1a	Csr,Etc	-
2N2530	Si-NPN	=2N2529:>10MHz,B>12	2a	Sty	BC167,BC182,BC237,BC547..
2N2531	Si-NPN	=2N2529:>12MHz,B>20	2a	Sty	BC167,BC182,BC237,BC547..
2N2532	Si-NPN	=2N2529:>16MHz,B>45	2a	Sty	BC167,BC182,BC237,BC547..
2N2533	Si-NPN	=2N2529:>10MHz,B>20	2a	Sty	BC167,BC182,BC237,BC547..
2N2534	Si-NPN	=2N2529:>20MHz,B>45	2a	Sty	BC167,BC182,BC237,BC547..
2N2535	Ge-PNP	AF-Pow,60V,3A,10W	49a	Rca	-
2N2536	Ge-PNP	=2N2535:80V	49a	Rca	-

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2N2537	Si-NPN	Sw,60V,0,8A,0,8W,<40/40,B>50	2a$	Mot,Sem,Tix	BSS27,BSV77,BSV95,2N5189..
2N2538	Si-NPN	=2N2537:B>100	2a$	Mot,Sem,Tix	BSS27,BSV77,BSV95,2N5189..
2N2539	Si-NPN	=2N2537:0,5W	2a$	Mot,Sem,Tix	2N4014
2N254	Ge-NPN	HF,20V,5mA,0,065W	?1a	Csr,Etc	-
2N2540	Si-NPN	=2N2537:0,5W,B>100	2a$	Mot,Sem,Tix	2N4014
2N2541	Ge-PNP	AF,Sw,30V,1A,0,215W,>10MHz	2a	USA	-
2N255	Ge-PNP	Sw,Pow,15V,Ueb=15V,3A,20W,0,2MHz	23a$	USA	AD149,AUY19..20,2N2137..46..
2N2551	Si-PNP	AF,Sw,150V,1A(ss),0,4W	2a	USA	BFT28,2N3636..37,2N5415
2N2552	Ge-PNP	=2N1038	2a$o	USA,Mot,Tix	→2N1038
2N2553	Ge-PNP	=2N1039	2a$o	USA,Mot,Tix	→2N1039
2N2554	Ge-PNP	=2N1040	2a$o	USA,Mot,Tix	→2N1040
2N2555	Ge-PNP	=2N1041	2a$o	USA,Mot,Tix	→2N1041
2N2556	Ge-PNP	=2N1038	2a$o	USA,Mot,Tix	→2N1038
2N2557	Ge-PNP	=2N1039	2a$o	USA,Mot,Tix	→2N1039
2N2558	Ge-PNP	=2N1040	2a$o	USA,Mot,Tix	→2N1040
2N2559	Ge-PNP	=2N1041	2a$o	USA,Mot,Tix	→2N1041
2N255A	Ge-PNP	=2N255:5A	23a$	-	AL102..103,AUY21..22,2N1539..48..
2N256	Ge-PNP	Sw,Pow,30V,3A,20W,0,2MHz	23a$	USA	AD149,AUY19..20,2N2137..46..
2N2560	Ge-PNP	=2N1042	2a$o	USA,Mot,Tix	→2N1042
2N2561	Ge-PNP	=2N1043	2a$o	USA,Mot,Tix	→2N1043
2N2562	Ge-PNP	=2N1044	2a$o	USA,Mot,Tix	→2N1044
2N2563	Ge-PNP	=2N1045	2a$o	USA,Mot,Tix	→2N1045
2N2564(/5)	Ge-PNP	=2N1042	2a$	USA,Mot,Tix	→2N1042
2N2565(/5)	Ge-PNP	=2N1043	2a$	USA,Mot,Tix	→2N1043
2N2566(/5)	Ge-PNP	=2N1044	2a$	USA,Mot,Tix	→2N1044
2N2567(/5)	Ge-PNP	=2N1045	2a$	-	→2N1045
2N2568	Ge-NPN	HF-Pow,32V,0,1A,>1400MHz	5go	Mot	-
2N2569	Si-NPN	Chopper,20V,0,1A,0,3W,>100MHz	2a$	Amp,Phi	2N2432,2N4138
2N256A	Ge-PNP	=2N256:5A	23a$	-	AL102..103,AUY21..22,2N1539..48..
2N257	Ge-PNP	AF,Sw-Pow,40V,3A,30W	23a$	USA,Itt	AD149,AUY19..20,2N2143.46..
2N2570	Si-NPN	Chopper,20V,0,1A,0,3W,>100MHz	2a$	Amp,Phi	2N2432,2N4138
2N2571	Si-NPN	Chopper,20V,0,5A,0,3W,>100MHz	2a$	Amp	-
2N2572	Si-NPN	Chopper,20V,0,5A,0,3W,>100MHz	2a$	Amp	-
2N2573	Thy-50Hz	25V,17A(Tc=85°),Igt/Ih<40/10mA	23a$	Mot,Sld	2N3668
2N2574	Thy-50Hz	=2N2573:50V	23a$	-	2N3668
2N2575	Thy-50Hz	=2N2573:100V	23a$	-	2N3668
2N2576	Thy-50Hz	=2N2573:200V	23a$	-	2N3669
2N2577	Thy-50Hz	=2N2573:300V	23a$	-	2N3670
2N2578	Thy-50Hz	=2N2573:400V	23a$	-	2N3670
2N2579	Thy-50Hz	=2N2573:500V	23a$	-	-
2N258	Si-PNP	GenP,30/30V,0,05A,0,25W,a>15	2a	Ray	BC213,BC258,BC308,BC558..
2N2580(M)	Si-NPN	Sw,Pow,400/400V,10A,150W,B>10	38a$	Del,Stc	-
2N2581	Si-NPN	=2N2580:B>25	38a$	Del,Stc	-
2N2582	Si-NPN	Sw,Pow,500/500V,10A,150W,B>10	38a$	Del,Stc	-
2N2583	Si-NPN	=2N2582:B>25	38a$	Del,Stc	-
2N2584	Si-NPN	Sw,Pow,600/600V,10A,150W,B>10	38a$	Stc	-
2N2585	Si-NPN	=2N2584:B>25	38a$	Stc	-
2N2586	Si-NPN	AF-Pre,LN,60V,0,03A,0,3W,63MHz	2a$	USA,EUR,Mic	2N2483..84,2N3117,2SC2240,2SC2390..
2N2587	Ge-PNP	UHF,30V,0,1A,0,15W,>320MHz	2a	Mot	2N3283..86
2N2588	Ge-PNP	HF,40V,0,03A,0,15W,>75MHz	2a	TI	AF106,AF109R,AF306
2N2589	Si-NPN	Sw,Pow,150/150V,7A,85W	49a$	Stc	2N5542
2N259	Si-PNP	=2N258:a>32	2a	Ray	BC213,BC258,BC308,BC558..
2N2590	Si-PNP	GenP,100V,0,05A,0,4W,>50MHz,B>40	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2591	Si-PNP	=2N2590:>70MHz,B>70	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2592	Si-PNP	=2N2590:>90MHz,B>115	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2593	Si-PNP	=2N2590:>110MHz,B>160	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2594	Si-NPN	AF,Sw,80V,1A,1W,>40MHz	2a$	USA,Tix	BC140..141,2N1990,2N2102,2N2405..
2N2595	Si-PNP	GenP,80V,0,05A,0,4W,>30MHz,B>15	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2596	Si-PNP	=2N2595:>40MHz,B>30	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2597	Si-PNP	=2N2595:>60MHz,B>60	2a$	USA	BSS68,BSV68,2SA970,2SB715..16..
2N2598	Si-PNP	GenP,125V,0,05A,0,4W,>30MHz,B>20	2a$	USA	BF398,2SA970,2SA1049,2SB716(A)..
2N2599(A)	Si-PNP	=2N2598:>40MHz,B>40	2a$	USA	BF398,2SA970,2SA1049,2SB716(A)..
2N26	Ge-PNP	AF,Sw,40V,Ueb=40V,0,04A,0,09W	-	Wes	(ACY39,ASY48,ASY77,2N2042..43)
2N260	Si-PNP	GenP,10V,0,05A,0,2W,1,8MHz	?2e	Clv	BC213,BC258,BC308,BC558..

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2N2600(A)	Si-PNP	=2N2598: >60MHz, B>60	2a$	USA	BF398, 2SA970, 2SA1049, 2SB716(A)..
2N2601	Si-PNP	GenP, 60V, 0,05A, 0,4W, >20MHz, B>18	2a$	USA	BSS68, BSV68, 2SA970, 2SB715..716..
2N2602	Si-PNP	=2N2601: >40MHz, B>36	2a$	USA	BSS68, BSV68, 2SA970, 2SB715..716..
2N2603	Si-PNP	=2N2601: >60MHz, B>76	2a$	USA	BSS68, BSV68, 2SA970, 2SB715..716..
2N2604	Si-PNP	AF, Sw, LN, 60V, 0,03A, 0,4W, >30MHz	2a$	USA, EUR, Mic ..	2SA970, 2SA1016, 2SA1038..39, 2SA1136,..
2N2605(A)	Si-PNP	AF, Sw, LN, 60V, 0,03A, 0,4W, >30MHz	2a$	USA, EUR, Mic ..	2SA970, 2SA1016, 2SA1038..39, 2SA1136,..
2N2606	P-FET	GenP, 30V, Idss>0,1mA, Up<4V	2a&	USA, Mot, Tix	2N5797
2N2607	P-FET	GenP, 30V, Idss>0,3mA, Up<4V	2a&	USA, Mot, Tix	2N5020
2N2608	P-FET	GenP, 30V, Idss>0,9mA, Up<4V	2a&	USA, Mot, Tix	2N5460
2N2609	P-FET	GenP, 30V, Idss>2mA, Up<4V	2a&	USA, Mot, Tix	2N5461
2N260A	Si-PNP	=2N260: 30V	?2e	-	BC213, BC258, BC308, BC558..
2N261	Si-PNP	GenP, 75V, 0,05A, 0,2W, 1,8MHz	?2e	Clv	BC212, BC256, BC266, BC556..
2N2610	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W	?1a	USA	BC167, BC182, BC237, BC547..
2N2611	Si-NPN	AF, Sw, 120V, 1A, >4MHz	43a$	Sca, Ssi	(BD424, BD524, 2SC2384, 2SC2481,..)
2N2612	Ge-PNP	AF, Sw-Pow, 65V, 15A, 75W	23a$	USA	2N1551..52, 2N1555..56, 2N1559..60
2N2613	Ge-PNP	AF, 30V, 0,05A, 0,12W	2a	Rca, Spe	AC125..126, AC151, 2SB54, 2SB56
2N2614	Ge-PNP	AF, 40V, 0,05A, 0,12W	2a	Rca, Spe	2N1191..94, 2SB56A
2N2615	Si-NPN	VHF/IF, 30V, 0,3W, >500MHz	2a$	USA, Sgs	BF224..225, BFR37, BFW30, BFX73..
2N2616	Si-NPN	VHF/IF, 30V, 0,05A, 0,3W, >600MHz	2a$	USA, Sgs	BF224..225, BFR37, BFW30, BFX73..
2N2617	Si-NPN	AF, 25V, 0,1A, 0,25W	1a	Phc	BC168, BC183, BC238, BC548..
2N2618	Si-NPN	GenP, 60V, 0,75A, 0,6W, >200MHz	2a$	Syl	BC140..141, BC300..302, 2N2218..19..
2N2618/46	Si-NPN	=2N2618: 0,4W	2a$	-	BC337A, BC637, BC639, 2SD667..
2N262	Si-PNP	GenP, 10V, 0,05A, 0,2W, 6MHz	?2e	Clv	BC213, BC258, BC308, BC558..
2N2620	N-FET	GenP, 50V, Idss<50mA, Up<20V	2b&	Tdy	-
2N2621	Ge-PNP	AF/HF, 15V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2622	Ge-PNP	=2N2621: 24V, >15MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2623	Ge-PNP	=2N2621: 32V, >16MHz, B>20	2a	Cen, Sty	ASY26, 2N1309
2N2624	Ge-PNP	AF/HF, 16V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2625	Ge-PNP	=2N2624: 24V, >15MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2626	Ge-PNP	=2N2624: 32V, >16MHz, B>20	2a	Cen, Sty	ASY26, 2N1309
2N2627	Ge-PNP	AF/HF, 15V, 0,1A, 0,15W, >13MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2628	Ge-PNP	=2N2627: 24V, >15MHz, B>15	2a	Cen, Sty	ASY26..27, 2N1309
2N2629	Ge-PNP	=2N2627: 32V, >16MHz, B>20	2a	Cen, Sty	ASY26, 2N1309
2N262A	Si-PNP	=2N262: 30V	?2e	-	BC213, BC258, BC308, BC558..
2N263	Si-NPN	GenP, 45V, 0,02A, 0,15W, B>45, 20MHz	?1a	USA, Tix	BC167, BC182, BC237, BC547..
2N2630	Ge-PNP	Sw, 18V, 0,1A, 0,3W, >300MHz	2a$	Ssi, Sty	-
2N2631	Si-NPN	VHF-A/Dr, 80V, 1,5A, Pq>3W(150MHz)	2a$	USA, Rca, Tix	BFS23
2N2632	Si-NPN	Sw, Pow, 90/60V, 5A, 40W, >20MHz	49a$	USA	2N5002, 2N5004, 2N5284..85
2N2633	Si-NPN	=2N2632: 120/80V	49a$	USA	2N5284..85
2N2634	Si-NPN	=2N2632: 150/100V	49a$	USA	2N5284..85
2N2635	Ge-PNP	Sw, 30V, 0,1A, 0,15W, >150MHz	2a$	USA, Mot, Tix	2N2955..57
2N2636	Ge-PNP	Sw, Pow, 100V, 25A, 100W	23a$	USA	2N1652..53, 2N2286..87
2N2637	Ge-PNP	Sw, Pow, 100V, 25A, 100W	23a$	USA	2N1652..53, 2N2286..87
2N2638	Ge-PNP	Sw, Pow, 100V, 25A, 100W	23a$	USA	2N1652..53, 2N2286..87
2N2639	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N264	Si-NPN	=2N263: B>20	?1a	USA, Tix	BC167, BC182, BC237, BC547..
2N2640	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N2641	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N2642	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N2643	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N2644	Si-NPN	Dual, LN, 45V, 0,03A, 0,5W, >40MHz	81bs	USA, EUR	BFY81, 2N2913..20
2N2645	Si-NPN	GenP, 75V, 0,5A, 0,5W, >50MHz	2a$	USA, Sgs	BC639, BCX24, 2N3700..01, 2SD667..
2N2646	UJT-P	Ip<5µA, Iv>4mA	5r$	Gen, Mot, Phi	2N4871
2N2646P	UJT-P	Ip<12µA, Iv>4mA	5r$	Ssc	-
2N2647	UJT-P	=2N2646: Ip<2?A, Iv>8mA	5r$	-	-
2N2648	Ge-PNP	AF, Sw, 30V, 1A, 0,3W, >10MHz	2a$	Csr, Idi	-
2N2649	Si-NPN	AF, Sw, 65V, 1A, 0,7W, >100MHz	2a$	Nsc	-
2N265	Ge-PNP	AF, Sw, 25V, 0,05A, 0,075W, 1,5MHz	1a&	Csr, Etc	AC125..126, AC151, ASY26..27
2N2650	Si-NPN	=2N2649: 140V	2a$	Nsc	-
2N2651	Si-NPN	Sw, 40V, 0,5A, 0,36W, >350MHz	2a$	USA, Fch	BSS10, BSX26, BSX39, 2N3261
2N2652(A)	Si-NPN	Dual, 100V, 0,5A, 0,6W, >60MHz	81bs	USA, Mot	BFX70..72, 2N2060, 2N2223
2N2654	Ge-PNP	VHF, 25V, 10mA, 0,1W, 250MHz	5g	Amp, Phc	AF109R, AF139, AF239(S)
2N2655	Si-NPN	AF, Sw, 100V, 0,5A, 15W(Tc=25°)	2a$	Sca, Tra	BUX49, BUY41, 25C1860
2N2656	Si-NPN	HF, 25V, 0,2A, 0,36W, >250MHz	2a$	Trw	BC168, BC183, BC238, BC548..

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2N2657	Si-NPN	AF,Sw,80V,5A,4W(Tc=100°),>20MHz	2a$	USA,Nsc,Tix	BFT32..34,2N4895..97,2N5336..39
2N2658	Si-NPN	=2N2657:100V	2a$	USA,Nsc,Tix	BFT33..34,2N4895..97,2N5339
2N2659	Ge-PNP	AF,Sw-Pow,50V,3A,15W(Tc=25°)	2a$	USA,Tix	2N1039
2N266	Ge-PNP	AF,Sw,18V,0,2A,0,075W,0,8MHz	1a&	Gen	AC125..126,AC151,ASY26..27
2N2660	Ge-PNP	=2N2659:70V	2a$	USA,Tix	2N1040
2N2661	Ge-PNP	=2N2659:90V	2a$	USA,Tix	2N1041
2N2662	Ge-PNP	AF,Sw-Pow,50V,3A,15W(Tc=25°)	2a$o	USA,Tix	2N2553,2N2561
2N2663	Ge-PNP	=2N2662:70V	2a$o	USA,Tix	2N2554,2N2562
2N2664	Ge-PNP	=2N2662:90V	2a$o	USA,Tix	2N2555,2N2563
2N2665	Ge-PNP	AF,Sw-Pow,50V,3A,15W(Tc=25°)	2a$	USA,Tix	2N1039
2N2666	Ge-PNP	=2N2665:70V	2a$	USA,Tix	2N1040
2N2667	Ge-PNP	=2N2665:90V	2a$	USA,Tix	2N1041
2N2668	Ge-PNP	AF,Sw-Pow,50V,3A,15W(Tc=25°)	2a$o	USA,Tix	2N2553,2N2561
2N2669	Ge-PNP	=2N2668:70V	2a$o	USA,Tix	2N2554,2N2562
2N267	Ge-PNP	HF,35V,10mA,0,035W,30MHz	4g	Ray,Sty	AF124..127,AF200
2N2670	Ge-PNP	=2N2668:90V	2a$o	USA,Tix	2N2555,2N2563
2N2671	Ge-PNP	VHF,25V,10mA,0,1W,>200MHz	5g	Amp	AF106,AF109R,AF306
2N2672(A)	Ge-PNP	HF,25..32V,10mA,0,1W,>18MHz	2a	Amp	AF124..127,AF200
2N2673	Si-NPN	GenP,60V,0,025A,0,25W,40MHz,B>8	2a	Gen	BC174,BC182,BC190,BC546..
2N2674	Si-NPN	=2N2673:B>12	2a	Gen	BC174,BC182,BC190,BC546..
2N2675	Si-NPN	=2N2673:B>22	2a	Gen	BC174,BC182,BC190,BC546..
2N2676	Si-NPN	=2N2673:B>45	2a	Gen	BC174,BC182,BC190,BC546..
2N2677	Si-NPN	=2N2673:45V,B>20	2a	Gen	BC167,BC182,BC237,BC547..
2N2678	Si-NPN	=2N2673:45V,B>45	2a	Gen	BC167,BC182,BC237,BC547..
2N2679	Thy-50Hz	30V,0,35A(Tc=55°),Igt/Ih<0,02/<0,5mA	2a$	USA,Mot,Tag	(2N2323A)
2N2679A..2686A	Thy-Fast	=2N2679..2686:<10µS	2a$	-	-
2N268(A)	Ge-PNP	AF,Sw-Pow,80V,Ueb=40V,3A,30W	23a$	USA,Itt	AL102..103,AUY20,2N2141,2N2146..
2N2680	Thy-50Hz	=2N2679:60V	2a$	-	(2N2324A)
2N2681	Thy-50Hz	=2N2679:100V	2a$	-	(2N2324A)
2N2682	Thy-50Hz	=2N2679:200V	2a$	-	(2N2326A)
2N2683	Thy-50Hz	30V,0,28A(Tc=55°),Igt/Ih<0,02/<1mA	2a$	USA,Mot,Tag	(2N2323A)
2N2684	Thy-50Hz	=2N2683:60V	2a$	-	(2N2324A)
2N2685	Thy-50Hz	=2N2683:100V	2a$	-	(2N2324A)
2N2686	Thy-50Hz	=2N2683:200V	2a$	-	(2N2326A)
2N2687	Thy-50Hz	30V,0,28A(Tc=55°),Igt/Ih<0,2/<2mA	2a$	USA,Mot,Tag	2N6605,TAG06Y,(2N2323,TAG615-100)
2N2688	Thy-50Hz	=2N2687:60V	2a$	-	2N6606,TAG06YY,(2N2324,TAG615-100)
2N2689	Thy-50Hz	=2N2687:100V	2a$	-	2N6607,TAG06A,(2N2324,TAG615-100)
2N269(A)	Ge-PNP	Sw,20V,0,1A,0,12W,>4MHz	2a	Csr,Etc,Sty	ASY26..27,ASY48,ASY76..77
2N2690	Thy-50Hz	=2N2687:200V	2a$	-	2N6608,TAG06B,(2N2326,TAG615-200)
2N2691	Ge-PNP	AF,Sw-Pow,100V,20A,100W	23a$	USA	2N1652..53,2N2286..87
2N2691A	Ge-PNP	=2N2691:120V	23a$	-	2N1653,2N2287
2N2692	Si-NPN	GenP,45V,0,05,0,3W,>42MHz,B>90	2a$	USA,Tix	BC167,BC182,BC237,BC547..
2N2693	Si-NPN	=2N2692:B>60	2a$	USA,Tix	BC167,BC182,BC237,BC547..
2N2694	Si-NPN	=2N2692:B>30	2a$	USA,Tix	BC167,BC182,BC237,BC547..
2N2695	Si-PNP	AF,Sw,25V,0,5A,0,36W,>100MHz	2a$	USA,Sgs,Tix	BC327..328,BC636,2N2906..07(A)..
2N2696	Si-PNP	AF,Sw,25V,0,5A,0,36W,>100MHz	2a$	USA,Sgs,Tix	BC327..328,BC636,2N2906..07(A)..
2N2697	Si-NPN	AF,Sw-Pow,80V,5A,10W(Tc=100°),>20MHz	-	Csr,Sem	(BDV10..12,2SC3253)
2N2698	Si-NPN	=2N2697:100V	-	Csr,Sem	(BDV10..12)
2N2699	Ge-PNP	Sw,15V,0,1A,0,15W,>300MHz	2a	Phc	2N705A,2N964(A),2N2635,2N2955..57
2N27	Ge-NPN	AF/HF,35V,0,05W,>1MHz	?1a	Wes	(AC127,ASY28)
2N270	Ge-PNP	AF,25V,0,075A,0,15W	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2706(MP)	Ge-PNP	AF-Driver,32V,0,2A,0,28W	2a	Amp,Phc	AC128,AC152..153,2SB324,2SB415
2N2707	Ge-P/N	=2N2430+2N2706gep	2a	Amp,Phc	AC127+AC128,AC127+AC152
2N2708	Si-NPN	VHF/UHF-Mix/Osc,>700MHz	5g	USA,Mot,Rca	BF377..378,BF689,BF763,2N2857..
2N2709	Si-PNP	AF,Sw,50V,0,05A,0,24W	2a	Ray,Sty	BC212,BC257,BC307,BC557..
2N271(A)	Ge-PNP	HF,30V,Ueb=20V,0,2A,0,15W,10MHz	?1a	Csr,Etc	ASY26..27,2N3323..25
2N2710	Si-NPN	Sw,40V,0,5A,0,36W,<20/35nS	2a$	USA,Mot	BSS10,BSX26,BSX39,2N3261
2N2711	Si-NPN	GenP,18V,0,1A,0,12W,B>30	7c	USA,Mic	BC168,BC183,BC238,BC548..
2N2712	Si-NPN	=2N2711:B>75	7c	USA,Mic	BC168,BC183,BC238,BC548..
2N2713	Si-NPN	GenP,18V,0,2A,0,36W,200MHz,B>30	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N2714	Si-NPN	=2N2713:B>75	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N2715	Si-NPN	GenP,18V,0,05A,0,2W,B>30	7c	Gen,Sem	BC168,BC183,BC238,BC548..
2N2716	Si-NPN	=2N2715:B>75	7c	Gen,Sem	BC168,BC183,BC238,BC548..
2N2717	Ge-PNP	Sw,25V,15mA,0,1W,>300MHz	2a	Idi,Ssi	(ASZ21,2N2635,2N2955..57)

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2N2718	Ge-PNP	Sw,20V,0,4A,0,24W,>150MHz	2a	USA	-
2N2719	Si-NPN	Sw,25V,0,2A,0,3W,200MHz	2a$	Cen,Syl	BC238,BC548,BSY62,2N706A..
2N272	Ge-PNP	AF,-/20V,0,1A,0,15W,1MHz	?1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2720	Si-NPN	Dual,80V,0,04A,0,6W,>80MHz	81bs	USA,Mot	BFX70..72,2N2060,2N2223
2N2721	Si-NPN	Dual,80V,0,04A,0,6W,>80MHz	81bs	USA,Mot	BFX70..72,2N2060,2N2223
2N2722	Si-NPN	Dual,LN,45V,0,04A,0,6W,>100MHz	81bs	USA,Mot,Nsc	BFY81,2N2639..44,2N2913..20
2N2723	Si-NPN-Darl	GenP,80V,0,04A,0,5W,B>2000	5r$	USA,Mot	-
2N2724	Si-NPN-Darl	=2723:B>7000	5r$	USA,Mot	-
2N2725	Si-NPN-Darl	=2723:45V	5r$	USA,Mot	-
2N2726	Si-NPN	Vid/Sw,200V,0,5A,1W,>15MHz,B>30	2a$	USA	BSS48,2N2440,2SD413,2SD576,2SD624
2N2727	Si-NPN	=2N2726:B>75	2a$	USA	BSS48,2N2440,2SD413,2SD576,2SD624
2N2728	Ge-PNP	Sw,Pow,15V,50A,170W	38a$	USA,Mot	2N4048..4053
2N2729	Si-NPN	HF/AF,30V,0,05A,0,3W,>600MHz	2a$	USA	BF377..378,BF689,BF763,2N2857..
2N273	Ge-PNP	AF,-/12V,0,1A,0,15W	?1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2730	Ge-PNP	Sw,Pow,80V,65A,170W	38a$	Gpd,Sem	2N4050,2N4053
2N2731	Ge-PNP	=2N2730:60V	38a$	Gpd,Sem	2N4049..4050,2N4052..4053
2N2732	Ge-PNP	=2N2730:40V	38a$	Gpd,Sem	2N4048..4050,2N4051..4053
2N2733	Ge-PNP	Sw,Pow,80V,65A,170W	38a$	Gpd,Sem	2N4050,2N4053
2N2734	Ge-PNP	=2N2733:60V	38a$	Gpd,Sem	2N4049..4050,2N4052..4053
2N2735	Ge-PNP	=2N2733:40V	38a$	Gpd,Sem	2N4048..4050,2N4051..4053
2N2736	Ge-PNP	Sw,Pow,80V,65A,170W	38a$	Gpd,Sem	2N4050,2N4053
2N2737	Ge-PNP	=2N2736:60V	38a$	Gpd,Sem	2N4049..4050,2N4052..4053
2N2738	Ge-PNP	=2N2736:40V	38a$	Gpd,Sem	2N4048..4050,2N4051..4053
2N2739	Si-NPN	Sw,Pow,50V,20A,200W	-	Sem,Ssi,Stc	-
2N274	Ge-PNP	HF,40V,10mA,0,12W,30MHz	4g	Csr	AF124..127,AF200
2N2740	Si-NPN	=2N2739:100V	-		-
2N2741	Si-NPN	=2N2739:150V	-		-
2N2742	Si-NPN	=2N2739:200V	-		-
2N2743	Si-NPN	=2N2739:250V	-		-
2N2744	Si-NPN	=2N2739:300V	-		-
2N2745	Si-NPN	Sw,Pow,50V,20A,200W	-	Sem,Ssi,Stc	-
2N2746	Si-NPN	=2N2745:100V	-		-
2N2747	Si-NPN	=2N2745:150V	-		-
2N2748	Si-NPN	=2N2745:200V	-		-
2N2749	Si-NPN	=2N2745:250V	-		-
2N2750	Si-NPN	=2N2745:300V	-		-
2N2751	Si-NPN	Sw,Pow,50V,20A,200W	-	Sem,Ssi,Stc	-
2N2752	Si-NPN	=2N2751:100V	-		-
2N2753	Si-NPN	=2N2751:150V	-		-
2N2754	Si-NPN	=2N2751:200V	-		-
2N2755	Si-NPN	=2N2751:250V	-		-
2N2756	Si-NPN	=2N2751:300V	-		-
2N2757	Si-NPN	Sw,Pow,50V,30A,200W	49a$	USA,Whs	2N6324..25
2N2758	Si-NPN	=2N2757:100V	49a$	-	2N6324..25
2N2759	Si-NPN	=2N2757:150V	49a$	-	2N6324..25
2N2760	Si-NPN	=2N2757:200V	49a$	-	2N6324..25
2N2761	Si-NPN	=2N2757:250V	49a$	-	2N6324..25
2N2762	Si-NPN	=2N2757:300V	49a$	-	2N6324..25
2N2763	Si-NPN	Sw,Pow,50V,30A,200W	49a$	USA,Whs	2N6324..25
2N2764	Si-NPN	=2N2763:100V	49a$	-	2N6324..25
2N2765	Si-NPN	=2N2763:150V	49a$	-	2N6324..25
2N2766	Si-NPN	=2N2763:200V	49a$	-	2N6324..25
2N2767	Si-NPN	=2N2763:250V	49a$	-	2N6324..25
2N2768	Si-NPN	=2N2763:300V	49a$	-	2N6324..25
2N2769	Si-NPN	Sw,Pow,50V,30A,200W	49a$	USA,Whs	2N6324..25
2N277	Ge-PNP	AF,Sw-Pow,40V,Ueb=20V,15A,170W	38a$	USA,Mot	2N1980..82,2N2075..82,2N2491..
2N2770	Si-NPN	=2N2769:100V	49a$	-	2N6324..25
2N2771	Si-NPN	=2N2769:150V	49a$	-	2N6324..25
2N2772	Si-NPN	=2N2769:200V	49a$	-	2N6324..25
2N2773	Si-NPN	=2N2769:250V	49a$	-	2N6324..25
2N2774	Si-NPN	=2N2769:300V	49a$	-	2N6324..25
2N2775	Si-NPN	Sw,Pow,50V,30A,200W	49a$	USA,Whs	2N6324..25
2N2776	Si-NPN	=2N2775:100V	49a$	-	2N6324..25
2N2777	Si-NPN	=2N2775:150V	49a$	-	2N6324..25

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2N2778	Si-NPN	=2N2775:200V	49a$	-	2N6324..25
2N2779	Si-NPN	=2N2775:250V	49a$	-	2N6324..25
2N278	Ge-PNP	=2N277:50V,Ueb=30V	38a$	USA,Mot	2N1980..82,2N2075..77,2N2491..
2N2780	Si-NPN	=2N2775:300V	49a$	-	2N6324..25
2N2781	Si-NPN	HF/Sw-Pow,75V,2A,15W,>140MHz	2a	USA	-
2N2782	Si-NPN	HF/Sw-Pow,100V,2A,15W,>140MHz	2a	USA	-
2N2783	Si-NPN	HF/Sw-Pow,100V,2A,15W,>140MHz	2a	USA	-
2N2784	Si-NPN	Fast-Sw,15V,0,3W,<9/9nS	2a$	USA	-
2N2785	Si-NPN-Darl	GenP,60V,0,2A,0,5W,B>2000	5r$	Gen,Mot,Ray	BFX67,2N999
2N2786(A)	Ge-PNP	HF,35V,0,15A,>225MHz	2a$	Amp,Sca,Spe	-
2N2787	Si-NPN	GenP,75V,0,8A,0,8W,300MHz,B>20	2a$	USA	BC140..141,BSW39,2N2218..19A..
2N2788	Si-NPN	=2N2787:B>40	2a$	USA	BC140..141,BSW39,2N2218..19A..
2N2789(S)	Si-NPN	=2N2787:B>100	2a$	USA	BC140..141,BSW39,2N2218..19A..
2N279	Ge-PNP	AF,-/20V,0,05A,0,125W,B>20,0,3MHz	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2790	Si-NPN	=2N2787:0,5W	2a$	USA	BC639,BSW63..64,2N2221..22A..
2N2791	Si-NPN	=2N2787:0,5W,B>40	2a$	USA	BC639,BSW63..64,2N2221..22A..
2N2792	Si-NPN	=2N2787:0,5W,B>100	2a$	USA	BC639,BSW63..64,2N2221..22A..
2N2793	Ge-PNP	Sw,Pow,75V,60A,170W	38a$	Cen	2N4050,2N4053
2N2794	P-FET	GenP,20V,Idss>1,5mA	2a&	old	2N2497..98,2N2500
2N2795	Ge-PNP	Sw,25V,0,1A,0,075W,450MHz	2a	Idi	(2N2635,2N2955..57)
2N2796	Ge-PNP	Sw,25V,0,1A,0,075W,450MHz	2a	Idi	(2N2635,2N2955..57)
2N2797	Ge-PNP	Sw,40V,0,1A,0,075W,>150MHz	2a	Spr	(2N2955..57)
2N2798	Ge-PNP	Sw,60V,0,1A,0,075W,>120MHz	2a	Spr	-
2N2799	Ge-PNP	Sw,30V,0,1A,0,075W,>120MHz	2a	Spr	(2N2635,2N2955..57)
2N28	Ge-NPN	AF/HF,30V,Ueb=20V,0,08A,0,5MHz	?1a	Wes	(AC127,ASY28)
2N280	Ge-PNP	=2N279:a>47	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2800(S)	Si-PNP	Sw,50V,0,8A,0,8W,34/130nS,B>30	2a$	USA,Mot	BSW40,2N2904..05(A),2N3468,2SA717,..
2N2801(S)	Si-PNP	=2N2800:B>75	2a$	USA,Mot	BSW40,2N2904..05(A),2N3468,2SA717,..
2N2802	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2803	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2804	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2805	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2806	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2807	Si-PNP	Dual,LN,25V,0,03A,0,5W,>60MHz	81bs	Mot,Tix,++	BFX36,2N3806..11,2N4015..16
2N2808	Si-NPN	UHF,30V,0,025A,0,2W,>1GHz	5g	Ray	BF377..378,BF689,BF763,2N2857..
2N2808A	Si-NPN	=2N2808:>1,5GHz	5g	-	BF377..378,BF689,BF763,2N2857..
2N2809	Si-NPN	UHF,30V,0,025A,0,2W,>1GHz	5g	Ray	BF377..378,BF689,BF763,2N2857..
2N2809A	Si-NPN	=2N2809:>1,3GHz	5g	-	BF377..378,BF689,BF763,2N2857..
2N281	Ge-PNP	AF,16V,0,125A,0,125W,0,35MHz	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2810	Si-NPN	UHF,24V,0,025A,0,2W,>1GHz	5g	Ray	BF377..378,BF689,BF763,2N2857..
2N2810A	Si-NPN	=2N2810:>1,3GHz	5g	-	BF377..378,BF689,BF763,2N2857..
2N2811	Si-NPN	Sw,Pow,80V,10A,70W,>15MHz,B>20	49a$	USA	2N5288..89,2N5542
2N2812	Si-NPN	=2N2811:B>40	49a$	USA	2N5288..89,2N5542
2N2813	Si-NPN	=2N2811:120V	49a$	USA	2N5288..89,2N5542
2N2814	Si-NPN	=2N2811:120V,B>40	49a$	USA	2N5288..89,2N5542
2N2815	Si-NPN	Sw,Pow,80V,20A,200W	49a$	USA,Tho	2N6324..25
2N2816	Si-NPN	=2N2815:100V	49a$	-	2N6324..25
2N2817	Si-NPN	=2N2815:150V	49a$	-	2N6324..25
2N2818	Si-NPN	=2N2815:200V	49a$	-	2N6324..25
2N2819	Si-NPN	Sw,Pow,80V,25A,200W	49a$	USA,Tho	2N6324..25
2N282	Ge-PNP	=2x2N281:gep.	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2820	Si-NPN	=2N2819:100V	49a$	-	2N6324..25
2N2821	Si-NPN	=2N2819:150V	49a$	-	2N6324..25
2N2822	Si-NPN	=2N2819:200V	49a$	-	2N6324..25
2N2823	Si-NPN	Sw,Pow,80V,30A,200W	49a$	USA,Tho	2N6324..25
2N2824	Si-NPN	=2N2823:100V	49a$	-	2N6324..25
2N2825	Si-NPN	=2N2823:150V	49a$	-	2N6324..25
2N2826	Ge-PNP	AF-Pow,-/15V,1A,7,5W	43a$	Gpd,Sem	(AD162)
2N2827	Ge-PNP	AF-Pow,40V,1,5A,7,5W	43a$	Del	-
2N2828	Si-NPN	Sw,Pow,80V,3A,40W	43a$	USA	2N5002,2N5004,2N5284..85
2N2829	Si-NPN	Sw,Pow,80V,3A,40W	43a$	USA	2N5002,2N5004,2N5284..85
2N283	Ge-PNP	AF,Sw,20V,0,01A,0,125W,0,5MHz	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2831	Si-NPN	HF,40V,0,2A,0,36W,>250MHz	2a	Trw	BC547,BFX94..95,2N2221..22(A)..
2N2832	Ge-PNP	AF,Sw-Pow,80V,20A,85W	23a$	USA,Mot	2N1652..53,2N2286..87

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2N2833	Ge-PNP	=2N2832:120V	23a$	USA,Mot	2N1653,2N2287
2N2834	Ge-PNP	=2N2832:140V	23a$	USA,Mot	-
2N2835	Ge-PNP	AF-Pow,32V,1A,16W(Tc=50°)	22a$	Gpd,Phc	(AD162)
2N2836	Ge-PNP	AF-Pow,55V,3,5A,37W	23a$	Gpd,Phc	AD149,AUY19..20,2N1545..48..
2N2837	Si-PNP	=2N2800:0,5W	2a$	USA,Mot	2N2906..07(A),2N4026..29
2N2838	Si-PNP	=2N2801:0,5W	2a$	USA,Mot	2N2906..07(A),2N4026..29
2N284	Ge-PNP	AF,Sw,32V,0,125A,0,125W,0,35MHz	1a	Csr,Etc	AC125..126,AC151,2SB54,2SB56
2N2840	UJT-P	Ip<10µA,Iv>0,24mA	5r$	Gen	-
2N2841	P-FET	GenP,30V,Idss>0,025mA,Up<1,7V	2a&	USA,Isi	2N5471..72
2N2842	P-FET	GenP,30V,Idss>0,065mA,Up<1,7V	2a&	USA,Isi	2N5472..73
2N2843	P-FET	GenP,30V,Idss>0,2mA,Up<1,7V	2a&	USA,Isi	2N5265
2N2844	P-FET	GenP,30V,Idss>0,44mA,Up<1,7V	2a&	USA,Isi	2N5020,2N5266..67
2N2845	Si-NPN	Sw,60V,0,8A,0,36W,<40/40nS,B>30	2a$	Mot,Sgs,Tix	2N4014
2N2846	Si-NPN	=2N2845:0,8W	2a$	Mot,Sgs,Tix	BSS27,BSV77,BSV95,2N5189..
2N2847	Si-NPN	=2N2845:B>40	2a$	Mot,Sgs,Tix	2N4014
2N2848	Si-NPN	=2N2845:0,8W,B>40	2a$	Mot,Sgs,Tix	BSS27,BSV77,BSV95,2N5189..
2N2849(-1)	Si-NPN	AF,Sw,100V,3A,0,85W,B>100	2a$	USA	BSX64,2N4239,2SC696,2SC2214
2N2849-2..2856-2	Si-NPN	=2N2849(-1)..2N2856(-1):	49a$	-	2N5002,2N5004,2N5284..85
2N2849-3..2856-3	Si-NPN	=2N2849(-1)..2N2856(-1):	?49a$	-	(BD241C,BD539C,BD937,2SD712,..)
2N284A	Ge-PNP	=2N284:60V	1a	-	ASY48,ASY77
2N285(A,B)	Ge-PNP	Pow,-/40V,3A,25(A,B:30)W(Tc=45°)	23a$	USA	AD149,AUY19..20,2N2143..46..
2N2850(-1)	Si-NPN	=2N2849:B>40	2a$	USA	BSX64,2N4239,2SC696,2SC2214
2N2851(-1)	Si-NPN	=2N2849:B>40	2a$	USA	BSX64,2N4239,2SC696,2SC2214
2N2852(-1)	Si-NPN	=2N2849:B>20	2a$	USA	BSX64,2N4239,2SC696,2SC2214
2N2853(-1)	Si-NPN	AF,Sw,60V,3A,0,85W,B>40	2a$	USA	BSX62..64,2N4238..39,2SC696,2SC2214
2N2854(-1)	Si-NPN	=2N2853:B>100	2a$	USA	BSX62..64,2N4238..39,2SC696,2SC2214
2N2855(-1)	Si-NPN	=2N2853:B>40	2a$	USA	BSX62..64,2N4238..39,2SC696,2SC2214
2N2856(-1)	Si-NPN	=2N2853:B>20	2a$	USA	BSX62..64,2N4238..39,2SC696,2SC2214
2N2857	Si-NPN	UHF-Pre-in/Mix/Osc,LN,30V,0,04A,0,2W,>1GHz	5g	USA,EUR,Mic	BF377..378,BF689,BF763,BFX63
2N2858	Si-NPN	AF,Sw,100V,3A,0,6W	2a$	USA	BSX64,2N4239,2SC696(A),2SC2214
2N2859	Si-NPN	=2N2858:120V	2a$	USA	2SC696A
2N2860	Ge-PNP	Sw,18V,0,15A,0,15W,>250MHz	2a$	Syl	2N2635,2N2955..57
2N2861	Si-PNP	GenP,LN,25V,0,1A,0,3W,>60MHz,B>50	2a$	USA,Tix	BC214,BC259,BC309,BC559..
2N2862	Si-PNP	=2N2861:>45MHz,B>25	2a$	USA,Tix	BC214,BC259,BC309,BC559..
2N2863	Si-NPN	VHF-Osc/Dr,60V,1A,0,8W,250MHz	2a$	Idi,Tix	BFS23,2SC2419
2N2864	Si-NPN	VHF-Osc/Dr,60V,1A,0,8W,250MHz	2a$	Idi,Tix	BFS23,2SC2419
2N2865	Si-NPN	VHF/UHF-Osc/Dr,25V,0,05A,>600MHz	5g	USA,Tix	BFR37,BFW30,BFX59,BFX73
2N2866	Si-NPN	AF,Sw-Pow,120V,2A,40W,B>20	?49	USA	2N5284..85
2N2867	Si-NPN	=2N2866:B>40	?49	USA	2N5284..85
2N2868	Si-NPN	GenP,60V,1A,0,8W,>50MHz	2a$	USA,Sgs	BC140..141,BC300..302,2N1990..
2N2869	Ge-PNP	AF-Pow,60V,10A,30W	23a$	RCA	AL100..101,AUY21,2N2292..93..
2N2870	Ge-PNP	=2N2869:80V	23a$	USA,Rca	AL100..101,AUY37,2N2292..93..
2N2871	Si-PNP	Dual,Chopper,60V,0,2A(ss),0,4W	81bs	Hug	-
2N2872	Si-PNP	=2N2871:110V	81bs	Hug	-
2N2873	Ge-PNP	HF,35V,10mA,0,115W,>300MHz	5g	Rca,Sty	AF109R,AF139,AF239(S)
2N2874	Si-NPN	AF/HF-Pow,75V,2A,15W,>140MHz	2a	Sca,Ssi,Trw	(BD139,BD230,BD519,BD527,..)
2N2875	Si-PNP	AF,Sw-Pow,60V,2A,20W,>25MHz	?49	Sem,Ssi,Tra	2N5003,2N5005,2N5286..87
2N2876	Si-NPN	VHF-Pow,80V,2,5A,Pq>3W(150MHz)	49a	Rca,Sem	BLY35,2N3632
2N2877	Si-NPN	Sw,Pow,80V,5A,30W(Tc=100°),>30MHz,B>20	?49	USA,Tix	2N5002,2N5004,2N5284..85
2N2878	Si-NPN	=2N2877:>50MHz,B>40	?49	USA,Tix	2N5002,2N5004,2N5284..85
2N2879	Si-NPN	=2N2877:100V	?49	USA,Tix	2N5002,2N5004,2N5284..85
2N2880	Si-NPN	=2N2877:100V,>50MHz,B>40	?49	USA,Tix	2N5002,2N5004,2N5284..85
2N2881	Si-PNP	AF,Sw,60V,2A,8,5W(Tc=25°)	2a$	USA	BSS17..18,2N4235..36,2N5322..23
2N2882	Si-PNP	=2N2881:100V	2a$	USA	BSS17..18,2N4235..36,2N5322..23
2N2883	Si-NPN	VHF/UHF-Osc/Dr,40V,0,3A,Pq>0,5W(500MHz)	2a$	USA,Tix	BFS50,MRF515,MRF629,2N3948
2N2884	Si-NPN	=2N2883:Pq>0,75W(500MHz)	2a$	USA,Tix	BFS50,MRF515,MRF629,2N3948
2N2885	Si-NPN	Sw,40V,0,15W,>300MHz,<40/-nS	24b	Tra	BSS10..11,BSX19..20,2N2368..69(A),..
2N2886	Si-NPN	AF,Sw,50V,0,5A,0,8W	2a$	Trw	BC140..141,BC300..302,2N3053..
2N2887	Si-NPN	HF-Pow,100V,1,2A,25W,>140MHz	49a	USA	-
2N2888	Thy-50Hz	200V,16A(Tc=65°),Igt/<40mA	21b$	USA,Tag	2N685,T12N200,MCR3935-4,C35B..
2N2889	Thy-50Hz	=2N2888:250V	21b$	-	2N686,T12N300,MCR3935-5,C35H..
2N2890	Si-NPN	AF,Sw,100V,2A,0,8W,>30MHz,B>30	2a$	USA,Nsc,Tho	BSX64,2N4239,2SC696(A),2SC2214
2N2891	Si-NPN	=2N2890:B>50	2a$	USA,Nsc,Tho	BSX64,2N4239,2SC696(A),2SC2214
2N2892	Si-NPN	Sw,Pow,100V,5A,30W,>30MHz,B>30	49a$	USA,Tix	2N5002,2N5004,2N5284..85

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2N2893	Si-NPN	=2N2892: B>50	49a$	USA,Tix	2N5002, 2N5004, 2N5284..85
2N2894	Si-PNP	Sw, 12V, 0,2A, 1,2W, 60/90nS	2a$	USA,EUR	BFX36
2N2894A	Si-PNP	Sw, 12V, 0,2A, 0,36W, 23/34nS	2a$	USA,EUR	BFX36
2N2895	Si-NPN	GenP, 120V, 1A, 0,5W, >120MHz	2a$	USA,Mot,Rca	BCX22, 2N3700..01, 2SC2235, 2SD667..
2N2896	Si-NPN	GenP, 140V, 1A, 0,5W, >120MHz	2a$	USA,Mot,Rca	2N3700..01, 2SC2383, 2SC3228
2N2897	Si-NPN	GenP, 60V, 1A, 0,5W, >120MHz	2a$	USA,MOt,Rca	BC337A, BC637, BC639, 2SD667..
2N2898	Si-NPN	=2N2895	2a$	USA,Mot,Rca	→2N2895
2N2899	Si-NPN	=2N2896	2a$	USA,Mot,Rca	→2N2896
2N29	Ge-NPN	AF/HF, 35V, Ueb=20V, 0,1A, 0,12W, 2MHz	?1a	Wes	(AC127, ASY28)
2N290	Ge-PNP	Sw, Pow, 70V, Ueb=60V, 12A, 55W, 0,4MHz	38a$	Del	2N1981..82, 2N2079..80, 2N2490..
2N2900	Si-NPN	=2N2897	2a$	USA,Mot,Rca	→2N2897
2N2902	Si-NPN	Sw, Pow, 120V, 0,75A, 40W	-	TI	-
2N2903(A)	Si-NPN	Dual, 60V, 0,05A, 0,3W, >60MHz	81bs	USA,Mot,Sgs	BFY81, 2N2639..44, 2N2913..20
2N2904(S)	Si-PNP	GenP, 60/40V, 0,6A, 0,8W, >200MHz, B>40	2a$	USA,EUR,Mic	BSW40, 2N4030..33, 2N4036..37
2N2904A(AS)	Si-PNP	=2N2904: 60/60V	2a$	-	BSW40, 2N4030..33, 2N4036..37
2N2906(A)	Si-PNP	=2N2904: 0,4W	2a$	USA,EUR,Mic	2N4026..29
2N2906A	Si-PNP	60V, 0.6A, 0.4W, B=45/100	-		-
2N2907	Si-PNP	-	46	Nsc	→2N2907
2N2907(A)	Si-PNP	=2N2904: 0,4W, B>100	2a$	USA,EUR,Mic	2N4026..29
2N2907A	Si-PNP	60V, 0.6A, 0.4W, B=45/100	-		-
2N2908	Si-NPN	Sw, Pow, 80V, 5A, 45W	-	Sty	2N1722..23, (BD243B, BD539B, BD951..)
2N2909	Si-NPN	GenP, 60V, 1A, 0,4W, >50MHz	2a$	Sca,Ssi	BC337A, BC637, BC639, 2SD667..
2N291	Ge-PNP	AF, 25V, 0,2A, 0,18W	?1a	Csr,Etc	AC125..126, AC151, 2SB54, 2SB56
2N2910	Si-NPN	Dual, 45V, 0,3W, >55MHz	81bs	Gen,Ssi,++	BFX70..72, 2N2060, 2N2223, 2N3409..11
2N2911	Si-NPN	Sw, 150V, 3A, 5W(Tc=25°)	2a$	USA	BUX49, BUY41
2N2912	Ge-PNP	Sw, Pow, 15V, 25A, 75W(Tc=35°)	2a$	Gpd,Mot	-
2N2913	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	USA,Mot,Nsc	BFY81, 2N2639..44
2N2914	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2915(A)	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2916(A)	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2917	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2918	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2919(A)	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N292	Ge-NPN	HF, 15V, 0,02A, 0,065W, 5MHz	?1a	Csr,Etc,Sem	-
2N2920(A)	Si-NPN	Dual, LN, 45V, 0,03A, >60MHz	81bs	-	BFY81, 2N2639..44
2N2921	Si-NPN	GenP, 25V, 0,1A, 0,2W, 300MHz, B>35	7c	Sem,Tho	BC168, BC183, BC238, BC548..
2N2922	Si-NPN	=2N2921: a>55	7c	Sem,Tho	BC168, BC183, BC238, BC548..
2N2923	Si-NPN	=2N2921: a>90	7c	Gen,Tho,++	BC168, BC183, BC238, BC548..
2N2924	Si-NPN	=2N2921: a>150	7c	Gen,Tho,++	BC168, BC183, BC238, BC548..
2N2925	Si-NPN	=2N2921: a>235	7c	Gen,Tho,++	BC168, BC183, BC238, BC548..
2N2926	Si-NPN	25V, 0.1A, 0.2W, 300MHz, B>35	7c	Gen,Tho,++	BC168, BC183, BC238, BC548..
2N2927	Si-PNP	Sw, 25V, 0,5A, 0,8W, <75/170nS	2a$	USA,Sgs	2N3467..68, 2SA717, 2SA742
2N2928	Ge-PNP	HF, 15V, 0,1A, 0,15W, >400MHz	5g	Syf	2N3283..86, (AF139, AF239(S))
2N2929	Ge-PNP	VHF-Osc/Dr, 25V, 0,1A, 0,3W, 1100MHz	2a$	Idi,Mot	-
2N292A	Ge-NPN	=2N292: 0,1W	2a	-	-
2N293	Ge-NPN	HF, 15V, 0,02A, 0,065W, 8MHz	?1a	Csr,Etc,Sem	-
2N2930	Ge-PNP	AF, Sw, 30V, 0,5A, 0,25W, >4MHz	2a	USA	ASY76..77
2N2931	Si-NPN	Min, AF, 5V, 0,05A, 0,05W, >20MHz, B>30	?36c	Itt	BC121..123
2N2932	Si-NPN	=2N2931: a>70	?36c	Itt	BC121..123
2N2933	Si-NPN	=2N2931: a>45	?36c	Itt	BC121..123
2N2934	Si-NPN	=2N2931: 45V	?36c	Itt	BC123
2N2935	Si-NPN	=2N2931: 45V, a>70	?36c	Itt	BC123
2N2936	Si-NPN	Dual, 60V, 0,03A, 0,6W, >30MHz	81bs	Ray,Sem,Sty	BFY81, 2N2639..44, 2N2919..20
2N2937	Si-NPN	Dual, 60V, 0,03A, 0,6W, >30MHz	81bs	Ray,Sem,Sty	BFY81, 2N2639..44, 2N2919..20
2N2938	Si-NPN	Sw, 25V, 0,5A, 0,3W, >500MHz, <30/30nS	2a$	Etc,Fer	BSS10, BSX26, BSX28, BSX39, 2N3261
2N2939	Si-NPN	AF, Sw, 75V, 1A, 0,8W, >150MHz	2a$	Etc,Ssi,Tra	BC140..141, BSX45..47, 2N1990..
2N2940	Si-NPN	=2N2939: 120V	2a$	Etc,Ssi,Tra	BSS,42, BSW67, BSX47, 2N2405..
2N2941	Si-NPN	=2N2939: 150V	2a$	Etc,Ssi,Tra	BSS43, BSW68
2N2942	Ge-PNP	Sw, 50V, 0,1A, 0,15W, >150MHz	2a	Spr	-
2N2943	Ge-PNP	=2N2942: 30V, >120MHz	2a	Spr	2N2635, 2N2955..57
2N2944(A)	Si-PNP	Chopper, 15V, 0,1A, 0,4W, 15MHz	2a$	Mot,Tix,++	2N5229
2N2945(A)	Si-PNP	Chopper, 25V, 0,1A, 0,4W, 13MHz	2a$	Mot,Tix,++	2N5230
2N2946(A)	Si-PNP	Chopper, 25V, 0,1A, 0,4W, 12MHz	2a$	Mot,Tix,++	2N5231
2N2947	Si-NPN	HF-Pow, 60V, 1,5A, Pq=15W(50MHz)	23a$	Mot,Sca,Ssi	-

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2N2948	Si-NPN	HF-Pow,40V,1,5A,Pq=15W(30MHz)	23a$	Mot,Sca,Ssi	-
2N2949	Si-NPN	HF-Dr/Out,60V,0,7A,Pq=3,5W(50MHz)	2a	Mot,Sca,Ssi	-
2N2950	Si-NPN	HF-Dr/Out,60V,0,7A,Pq=3,5W(50MHz)	49a	Mot,Sca,Ssi	-
2N2951(S)	Si-NPN	HF-Ant/Dr,60V,0,25A,Pq=0,6W(50MHz)	2a$	Mot,Tix,++	BFX55,MRF229..230
2N2952	Si-NPN	HF-Ant/Dr,60V,0,25A,Pq=0,6W(50MHz)	2a$	Mot,Tix,++	(BFX55,MRF229..230)
2N2953	Ge-PNP	AF,Sw,30V,0,15A,0,12W,10MHz	2a	Cen,Spe,Sty	AC125..126,AC151,ASY26,ASY76..77
2N2954	Si-NPN	HF-Osc/Dr,30V,0,5A,0,2W,>300MHz	-	Phc	BFS51,BFQ42,BFR98,BFX55..
2N2955	Ge-PNP	Sw,40V,0,1A,0,15W,32/53nS	2a$	Idi,Mot,Ssi	-
2N2956	Ge-PNP	Sw,40V,0,1A,0,15W,25/55nS	2a$	Idi,Mot,Ssi	-
2N2957	Ge-PNP	Sw,40V,0,1A,0,15W,22/50nS	2a$	Idi,Mot,Ssi	-
2N2958(S)	Si-NPN	Sw,60V,0,6A,0,6W,<95/500nS,B>40	2a$	Mot,Sgs,++	BSW27..28,BSW51..54,2N2218..19(A),..
2N2959(S)	Si-NPN	=2N2958:B>100	2a$	Mot,Sgs,++	BSW27..28,BSW51..54,2N2218..19(A),..
2N296	Ge-PNP	AF,Sw-Pow,-/60V,Ueb=15V,2A,20W	23a$	USA	AL102..103,AUY19..20,2N2145..46..
2N2960	Si-NPN	Sw,60V,0,6A,0,6W,<95/500nS	2a$	Ray,Sem,Tra	BSW27..28,BSW51..54,2N2218..19(A),..
2N2961	Si-NPN	Sw,60V,0,6A,0,6W,<95/500nS	2a$	Ray,Sem,Tra	BSW27..28,BSW51..54,2N2218..19(A),..
2N2962	Ge-PNP	VHF-A/Dr,40V,0,3A,0,35W,>560MHz	?49a$	Sca,Spr	-
2N2963	Ge-PNP	VHF-A/Dr,40V,0,3A,0,35W,>560MHz	?49a$	Sca,Spr	-
2N2964	Ge-PNP	VHF-A/Dr,30V,0,3A,0,35W,>560MHz	?49a$	Sca,Spr	-
2N2965	Ge-PNP	VHF-A/Dr,30V,0,3A,0;35W,>560MHz	?49a$	Sca,Spr	-
2N2966	Ge-PNP	VHF,20V,0,1A,0,06W,>500MHz	-	Phc	2N3283..86,(AF139,AF239(S))
2N2967	Si-NPN	Fast-Sw,12V,0,3W,<15/15nS	2a$	Phc	BSS11..12,BSY17..18,2N2368..69(A),..
2N2968	Si-PNP	Chopper,30V,0,05A,0,15W,>10MHz	2a	USA	2N2946
2N2969	Si-PNP	Chopper,30V,0,05A,0,15W,>10MHz	2a	USA	2N2946
2N297(A)	Ge-PNP	AF,Sw-Pow,60V,Ueb=40V,4A,85W	23a$	USA,Mot	AL102..103,AUY21..22,2N1545..48..
2N2970	Si-PNP	Chopper,20V,0,05A,0,15W,>8MHz	2a	USA	2N2946
2N2971	Si-PNP	Chopper,20V,0,05A,0,15W,>8MHz	2a	USA	2N2946
2N2972	Si-NPN	=2N2913:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2973	Si-NPN	=2N2914:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2974	Si-NPN	=2N2915:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2975	Si-NPN	=2N2916:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2976	Si-NPN	=2N2917:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2977	Si-NPN	=2N2918:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2978	Si-NPN	=2N2919:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2979	Si-NPN	=2N2920:0,3W	81bq	USA,Mot,Sgs	BFW51..52
2N2980	Si-NPN	Dual,100V,0,5A,0,25W,>60MHz	81bq	USA,Mic,Sgs	(BFX70..72,2N2060,2N2223)
2N2981	Si-NPN	Dual,100V,0,5A,0,25W,>50MHz	81bq	USA,Mic,Sgs	(BFX70..72,2N2060,2N2223)
2N2982	Si-NPN	Dual,100V,0,5A,0,25W,>50MHz	81bq	USA,Mic,Sgs	(BFX70..72,2N2060,2N2223)
2N2983	Si-NPN	AF,Sw,155V,3A,1W,60MHz,B>20	2a$	USA	BUX49..53,BUY41,2SD625
2N2984	Si-NPN	=2N2983:185V	2a$	USA	BUX50..53,2SD625
2N2985	Si-NPN	=2N2983:B>40	2a$	USA	BUX49..53,BUY41,2SD625
2N2986	Si-NPN	=2N2983:185V,B>40	2a$	USA	BUX50..53,2SD625
2N2987	Si-NPN	AF,Sw,95V,1A,15W(Tc=100°),B>25	2a$	USA,Tix	BUX49..53,BUY41,2SD625
2N2988	Si-NPN	=2N2987:155V	2a$	USA,Tix	BUX49..53,2SD625
2N2989	Si-NPN	=2N2987:B>60	2a$	USA,Tix	BUX49..53,BUY41,2SD625
2N299	Ge-PNP	HF,5V,5mA,0,02W,110MHz	2a	Phc	AF106,AF109R,AF124..125,AF200
2N2990	Si-NPN	=2N2987:155V,B>60	2a$	USA,Tix	BUX49..53,2SD625
2N2991	Si-NPN	=2N2987:	49a$	USA,Tix	(2SC2275(A),2SC2528..29,2SD608,..)
2N2992	Si-NPN	=2N2988:	49a$	USA,Tix	(2SC2275A,2SC2529,2SD608,2SD759,..)
2N2993	Si-NPN	=2N2989:	49a$	USA,Tix	(2SC2275(A),2SC2528..29,2SD608,..)
2N2994	Si-NPN	=2N2990:	49a$	USA,Tix	(2SC2275A,2SC2529,2SD608,2SD759,..)
2N2995	Si-NPN	AF,Sw,120V,1A,>10MHz	49a$	USA	(2SC2275(A),2SC2528..29,2SD608,..)
2N2996	Ge-PNP	UHF,15V,0,05A,0,075W,>400MHz	5g	Ssi,Sty,Tix	AF139,AF239(S),2N3283..86
2N2997	Ge-PNP	UHF,30V,0,05A,0,075W,>400MHz	5g	Ssi,Sty,Tix	AF139,AF239(S),2N3283..86
2N2998	Ge-PNP	UHF,15V,0,05A,0,075W,>600MHz	5g	Sty,Tix	AF139,AF239(S),2N3283..86
2N2999	Ge-PNP	UHF,15V,0,05A,0,075W,>1400MHz	5g	Sty,Tix	-
2N30	Ge-PNP	AF/HF,30V,Ueb=50V,7mA,0,1W,2MHz	-	Gen	AF124..127,AF200
2N300	Ge-PNP	HF,5V,5mA,0,02W,95MHz	2a	Phc	AF106,AF109R,AF124..125,AF200
2N3000	Ge-PNP	AF,45V,0,4A,0,15W	2a	Stc,Sty	ASY76..77
2N3001	Thy-50Hz	30V,0,25A(Tc=55°),Igt/Ih<0,02/<3mA	2a$	USA,Mot,Tag	(2N2323A)
2N3002	Thy-50Hz	=2N3001:60V	2a$	-	(2N2324A)
2N3003	Thy-50Hz	=2N3001:100V	2a$	-	(2N2324A)
2N3004	Thy-50Hz	=2N3001:200V	2a$	-	(2N2326A)
2N3005	Thy-50Hz	=2N3001:Igt/Ih<0,2/<5mA	2a$	-	2N6605,TAG06Y,(2N2323,TAG615-100)
2N3006	Thy-50Hz	=2N3002:Igt/Ih<0,2/<5mA	2a$	-	2N6606,TAG06YY,(2N2324,TAG615-100)

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2N3007	Thy-50Hz	=2N3003:Igt/Ih<0,2/<5mA	2a$	-	2N6607,TAG06A,(2N2324,TAG615-100)
2N3008	Thy-50Hz	=2N3004:Igt/Ih<0,2/<5mA	2a$	-	2N6608,TAG06B,(2N2326,TAG615-200)
2N3009	Si-NPN	Sw,40V,0,2A,0,36W,<15/25nS	2a$	USA,Mot,Sgs	BSS10..11,BSX19..20,2N2368..69(A),..
2N301	Ge-PNP	AF,Sw-Pow,40V,3A,50W	23a$	USA,Mot	AD149,AUY19..20,2N2143..46..
2N3010	Si-NPN	Sw,15V,0,05A,0,3W,<12/12nS	2a$	USA,Mot,Sgs	BSS11..12,BSY17..18,2N2368..69(A),..
2N3011	Si-NPN	Fast-Sw,30V,0,2A,0,36W,<15/20ns	2a$	USA,Mot,Mic	BSS11..12,BSX19..20,2N2368..69(A),..
2N3012	Si-PNP	Sw,12V,0,2A,0,36W,<60/75ns	2a$	USA,Mot,Mic	BSX36
2N3013(R)	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<15/25ns	2a$	USA,Mot,Mic	BSS10..11,BSX19..20,2N2368..69(A),..
2N3014	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<16/25nS	2a$	=2N1313	BSS10..11,BSX19..20,2N2368..69(A),..
2N3015	Si-NPN	Sw,60V,1A,0,8W,<40/60nS	2a$	USA,Mot,Tix	BSS27,BSV77,BSV95,2N5189..
2N3016	Si-NPN	AF,Sw,100V,2,5A,3,3W(Tc=25°)	2a$	USA	BSX64,2N4239,2N5339,2SC696(A),2SC2214
2N3017	Si-NPN	=2N3016:5A	49a$	USA	(BD243C,BD539C,BD953,2SD613,..)
2N3018	Si-NPN	=2N3016:10A,25W(Tc=25°)	49a$	USA	2N5288..89,2N5542
2N3019(S)	Si-NPN	GenP,140V,1A,0,8W,>100MHz,B>100	2a$	USA,EUR,Mic	BSS43,BSW68,2SC1860
2N301A	Ge-PNP	=2N301:60V	23a$	-	AL102..103,AUY19..20,2N2144..46..
2N302	Ge-PNP	HF/Sw,30V,Ueb=20V,0,2A,0,15W,>7MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N3020(S)	Si-NPN	=2N3019:B>40	2a$	USA,EUR,Mic	BSS43,BSW68,2SC1860
2N3021	Si-PNP	AF,Sw-Pow,30V,3A,25W,>60MHz,B>20	23a$	USA,Mot,Tix	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3022	Si-PNP	=2N3021:45V	23a$	-	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3023	Si-PNP	=2N3021:60V	23a$	-	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3024	Si-PNP	=2N3021:B>50	23a$	-	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3025	Si-PNP	=2N3021:45V,B>50	23a$	-	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3026	Si-PNP	=2N3021:60V,B>50	23a$	-	2SA1141,2SA1146,2SA1186,2SA1292,BDW52C...
2N3027	Thy-Fast	30V,0,5A(Tc=100°),Igt<0,2mA	2a$	USA,Mot,Tag	(TAG64Y,BRX44,BR103,TAG60Y,TAG62Y)
2N3028	Thy-Fast	=2N3027:60V	2a$	-	(TAG64F,BRX46,BRX51,TAG60F,TAG62F)
2N3029	Thy-Fast	=2N3027:100V	2a$	-	(TAG64A,BRX46,BRX51,TAG60A,TAG62A)
2N303	Ge-PNP	=2N302:>14MHz	?1a	Csr,Etc	ASY26,2N3323..25
2N3030	Thy-Fast	=2N3027:Igt<0,02mA	2a$	-	-
2N3031	Thy-Fast	=2N3028:Igt<0,02mA	2a$	-	-
2N3032	Thy-Fast	=2N3029:Igt<0,02mA	2a$	-	-
2N3033	Si-NPN	Fast-Sw,160V,0,02A,0,3W,<5/-nS	2a$	Sca,Spe,Tix	-
2N3034	Si-NPN	=2N3033:120V	2a$	Sca,Spe,Tix	-
2N3035	Si-NPN	=2N3033:90V	2a$	Sca,Spe,Tix	-
2N3036	Si-NPN	AF,Sw,120V,1,2A,0,8W,89/575nS	2a$	USA,Tix	2N2102,2N2405,2N3019..20
2N3037	Si-NPN	AF,Sw,120V,0,5A,0,36W,>50MHz	24b	TI	BCX22,2N3700..01,2SD2235,2SD667..
2N3038	Si-NPN	=2N3037:100V	24b	TI	BC639,BCX24,2N3700..01,2SD667..
2N3039	Si-PNP	AF,Sw,50V,0,5A,0,36W,>50MHz	24b	TI	BC327,BC638,BC640,2SB647..
2N3040	Si-PNP	=2N3039:40V	24b	TI	BC327,BC636,BC638,BC640..
2N3043	Si-NPN	=2N2639:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3044	Si-NPN	=2N2640:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3045	Si-NPN	=2N2641:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3046	Si-NPN	=2N2642:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3047	Si-NPN	=2N2643:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3048	Si-NPN	=2N2644:0,35W	10-FLP/ch	Mot,Ray,Tix	-
2N3049	Si-PNP	Dual,LN,25V,0,1A,0,35W,>60MHz	10-FLP/ch	Mot,Sem,Sty	-
2N3050	Si-PNP	Dual,LN,25V,0,1A,0,35W,>60MHz	10-FLP/ch	Mot,Sem,Sty	-
2N3051	Si-PNP	Dual,LN,25V,0,1A,0,35W,>60MHz	10-FLP/ch	Mot,Sem,Sty	-
2N3052	Si-NPN	Dual,35V,0,2A,0,35W,>200MHz	10-FLP/ch	Ssi,Tix	-
2N3053(S)	Si-NPN	AF-Driver,60V,0,7A,1W,>100MHz	2a$	USA,EUR,Mic	BC140..141,BC300..302,2N2218..19..
2N3053A	Si-NPN	=2N3053:80V	2a$	Mot,Rca	BC140..141,BC300..302,2N2218..19A,..
2N3054(S)	Si-NPN	AF-Pow,90V,4A,25W,3MHz	22a$	USA,EUR,Mic	BD243B,BD539C,2N3767,2SD712..
2N3054A	Si-NPN	=2N3054:75W,>3MHz	22a$	Mot	BD243B,BD539C,2N3767,2SD712..
2N3055(S,U)	Si-NPN	AF,Sw-Pow,100V,15A,115W,>2,5MHz	23a$	USA,EUR	BD317,BD745C,BDW51C,2N5629..31,+
2N3055A	Si-NPN	AF,Sw-Pow,100V,15A,115W,<4,5/9µS	23a$	Mot	-
2N3055C	Si-NPN	AF,Sw-Pow,80V,15A,115W,>2,5MHz	23a$	STE	-
2N3055C,V	Si-N	=2N3055:80V	23a$	Sgs	BD315,BD745B,BDW51B,2N5629..31,+
2N3055E	Si-NPN	AF,Sw-Pow,100V,15A,115W,>2,5MHz	23a$	USA,EUR	-
2N3055H	Si-NPN	100V,15A,115W,800kHz	23a$	-	-
2N3055V	Si-NPN	AF,Sw-Pow,80V,15A,115W,>2,5MHz	23a$	STE	BD315,BD745B,BDW51B,2N5629..31..
2N3056	Si-NPN	GenP,100V,1A,0,4W,>80MHz,B>40	2a$	USA,Fch	BC639,BCX24,2N3700..01,2SD667..
2N3056A	Si-NPN	=2N3056:140V	2a$	-	2N3700..01,2SC2383,2SC3228
2N3057	Si-NPN	=2N3056:B>100	2a$	USA,Fch	BC639,BCX24,2N3700..01,2SD667..
2N3057A	Si-NPN	=2N3056:140V,B>100	2a$	-	2N3700..01,2SC2383,2SC3228
2N3058	Si-PNP	Sw,Chopper,6/6/6V,0,1A,0,4W	2a$	USA,Tdy	-

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2N3059	Si-PNP	Sw,Chopper,10/10/10V,0,1A,0,4W	2a$	USA,Tdy	-
2N306	Ge-NPN	AF,Sw,20V,2mA,0,05W,>0,6MHz	?1a	Csr,Etc	(AC127,ASY28..29)
2N3060	Si-PNP	Sw,Chopper,70/60/30V,0,1A,0,4W	2a$	USA,Tdy	-
2N3061	Si-PNP	Sw,Chopper,70/60/30V,0,1A,0,4W	2a$	USA,Tdy	-
2N3062	Si-PNP	Sw,Chopper,90/80/40V,0,1A,0,4W	2a$	Tdy	-
2N3063	Si-PNP	Sw,Chopper,90/80/40V,0,1A,0,4W	2a$	Tdy	-
2N3064	Si-PNP	Sw,Chopper,110/100/50V,0,1A,0,4W	2a$	Tdy	-
2N3065	Si-PNP	Sw,Chopper,110/100/50V,0,1A,0,4W	2a$	Tdy	-
2N3066(A)	N-FET	GenP,50V,Idss>0,8mA,Up<9,5V	2b&	Sol,Tix	-
2N3067(A)	N-FET	GenP,50V,Idss>0,2mA,Up<4,5V	2b&	Sol,Tix	-
2N3068(A)	N-FET	GenP,50V,Idss>0,05mA,Up<2,2V	2b&	Sol,Tix	2N4338
2N3069(A)	N-FET	GenP,50V,Idss>2mA,Up<10V	2b	Nsc,Sol,Tix	-
2N307(A,B)	Ge-PNP	AF,Sw-Pow,35V,5A,106W	23a$	USA,Mot	AL102..103,AUY21..22,2N3611..18,2N4341
2N3070(A)	N-FET	GenP,50V,Idss>0,5mA,Up<5V	2b	Nsc,Sol,Tix	-
2N3071	N-FET	GenP,50V,Idss>0,1mA,Up<2,5V	2b	Nsc,Sol,Tix	2N4338
2N3072	Si-PNP	Sw,60V,0,5A,0,8W,>130MHz,<40/100nS	2a$	USA,Mot,Sgs	BSW23,2N2904..05(A),2N3468,2SA742,..
2N3073	Si-PNP	=2N3072:0,36W	2a$	USA,Mot,Sgs	BSW24,2N2906..07(A),2N4026..29
2N3074	Ge-PNP	HF,30V,0,02A,0,14W	5g	Amp,Sty	AF139,AF239(S),2N3283..86
2N3075	Ge-PNP	HF,35V,0,02A,0,14W	5g	Amp,Sty	AF139,AF239(S),2N3283..86
2N3076	Si-NPN	Sw,Pow,140V,10A,125W,>50MHz	-	Sca,Ssi,Trw	BUX98A
2N3077	Si-NPN	GenP,LN,80V,0,05A,0,36W,>60MHz,B>80	2a$	USA	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2N3078	Si-NPN	=2N3077:B>25	2a$	USA	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2N3079	Si-NPN	Sw,Pow,200/200V,5A,150W,>2MHz	38a$	Del,Spc	-
2N308	Ge-PNP	HF,20V,5mA,0,03W	?1a	Csr,Etc	AF124..127,AF200
2N3080	Si-NPN	=2N3079:300/300V	38a$	Del,Spc	-
2N3081	Si-PNP	Sw,70V,0,6A,0,6W,>150MHz,<60/175nS	2a$	USA,Mot	BSW40,2N4031,2N4033,2N4036
2N3082	Si-NPN	Dual,Chopper,25V,0,1A,0,5W	81bu	Gen,Tho	-
2N3083	Si-NPN	Dual,Chopper,25V,0,1A,0,5W	81bu	Gen,Tho	-
2N3084	N-FET	GenP,30V,Idss>0,8mA,Up<10V	2f&	Sol,Tdy	2N4340
2N3085	N-FET	GenP,30V,Idss>0,8mA,Up<10V	2f&	Sol,Tdy	2N4340
2N3086	N-FET	GenP,40V,Idss>0,8mA,Up<10V	2f&	Sol,Tdy	2N4340
2N3087	N-FET	GenP,30V,Idss>0,8mA,Up<10V	2f&	Sol,Tdy	2N4340
2N3088(A)	N-FET	GenP,15V,Idss>0,5mA,Up<5V	2f&	Sol,Tdy	2N4338
2N3089(A)	N-FET	GenP,15V,Idss>0,5mA,Up<5V	2f&	Sol,Tdy	2N4338
2N309	Ge-PNP	HF,20V,5mA,0,03W	?1a	Csr,Etc	AF124..127,AF200
2N31	Ge-PNP	AF/HF,30V,Ueb=50V,7mA,0,1W,3MHz	-	Gen	AF124..127,AF200
2N310	Ge-PNP	HF,30V,5mA,0,03W	?1a	Csr,Etc	AF124..127,AF200
2N3107	Si-NPN	AF,Sw,100V,1A,0,8W,>70MHz,B>100	2a$	USA,Sgs,Tix	BC141,BSW66,BSX46..47,2N1990..
2N3108	Si-NPN	=2N3107:B>40	2a$	USA,Sgs,Tix	BC141,BSW66,BSX46..47,2N1990..
2N3109	Si-NPN	=2N3107:80V	2a$	USA,Sgs,Tix	BC140,BSW65,BSX45..47,2N1990..
2N311	Ge-PNP	Sw,15V,0,075W	2a	Csr,Etc,Sty	ASY26..27,ASY76..77
2N3110(S)	Si-NPN	=2N3107:80V,B>40	2a$	USA,Sgs,Tix	BC140,BSW65,BSX45..47,2N1990..
2N3112	P-FET	GenP,20V,Idss>0,035mA,Up<4V	5g+	Six	2N5797,J177
2N3113	P-FET	=2N3112:	2a$	Six	2N5797
2N3114(S)	Si-NPN	Vid,150V,0,2A,0,8W,>40MHz	2a$	USA,Mot,Tix	BF257..259,BF657..659,BFR57..59..
2N3115	Si-NPN	=2N2958:0,4W	2a$	USA,Mot,Mic	BSS26,BSV59,BSX49,2N2221..22(A),..
2N3116	Si-NPN	=2N2959:0,4W	2a$	USA,Mot,Mic	BSS26,BSV59,BSX49,2N2221..22(A),..
2N3117	Si-NPN	AF,Sw,LN,60V,0,05A,0,36W,>60MHz	2a$	USA,Sgs,Tix	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2N3118	Si-NPN	FM/VHF-A/Tr,85V,0,5A,Pq>0,4W(150MHz)	2a$	USA,Rca	BFW47,2N3553,2SC2852
2N3119	Si-NPN	Sw,100V,0,5A,1W,>250MHz,<40/700nS	2a$	USA,Rca	BSW39,2N3723
2N312	Ge-NPN	Sw,15V,0,2A,0,075W	2a	Csr,Etc,Sty	ASY28..29,ASY73..75
2N3120	Si-PNP	Sw,45V,0,5A,0,8W,>130MHz,<40/100nS	2a$	USA,Mot,Sgs	2N3468,2SA717,2SA742
2N3121	Si-PNP	=2N3120:0,36W	2a$	USA,Mot,Sgs	BSW24,BSX36
2N3122	Si-NPN	AF-Driver,50V,0,5A,0,8W,>60MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N3123	Si-NPN	HF/Sw,60V,0,5A,0,8W,>400MHz	2a$	Sty	BFW47,BSV77,BSV95,2N3553..
2N3124	Ge-PNP	AF,Sw-Pow,40V,15A,90W	23a$	Cen,Csr,Gpd	AUY29,2N1549..60
2N3125	Ge-PNP	AF,Sw-Pow,80V,3,3A,90W	23a$	Cen,Csr,Gpd	AL102..103,AUY20,2N2141,2N2146..
2N3126	Ge-PNP	AF,Sw-Pow,100V,15A,90W	23a$	Cen,Csr,Gpd	2N1552,2N1556,2N1560
2N3127	Ge-PNP	VHF/UHF,25V,0,05A,0,1W,>400MHz	5g	USA,Mot	AF139,AF239(S),2N3283..86
2N3128	Si-NPN	Min,AF,20V,0,1A,0,15W,>60MHz	?7c	Nsc	BC122..123,BC146
2N3129	Si-NPN	Min,AF,45V,0,1A,0,15W,>60MHz	?7c	Nsc	BC123
2N313	Ge-NPN	HF,15V,0,02A,0,065W,5MHz	2a	Gen	-
2N3130	Si-NPN	Min,AF,60V,0,1A,0,15W,>60MHz	?7c	Nsc	-
2N3131	Si-NPN	Min,Sw,40V,0,1A,0,15W,>250MHz	?7c	Nsc	-

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2N3132	Ge-PNP	AF,Sw-Pow,100V,5A,90W	23a$	Cen,Sty	AL102..103,2N1542..43,2N1547..48..
2N3133(S)	Si-PNP	HF/Sw,50V,0,6A,0,6W,26/70nS,B>40	2a$	USA,Mot,Phi	2N3468,2SA717,2SA742
2N3134(S)	Si-PNP	=2N3133:B>100	2a$	USA,Mot,Phi	2N3468,2SA717,2SA742
2N3135	Si-PNP	=2N3133:0,4W	2a$	USA,Mot,Phi	BSW24,BSX36
2N3136	Si-PNP	=2N3133:0,4W,B>100	2a$	USA,Mot,Phi	BSW24,BSX36
2N3137	Si-NPN	VHF/UHF-A/Dr,40V,0,15A,Pq=0,6W(250MHz)	2a$	USA,Mot,Tho	BFW16..17,BFS50,BFR36,2SC2852..
2N3137T	Si-NPN	=2N3137:0,5A	2a$	TI	BFS50,MRF629,2N3948,2SC2852..
2N3138	Si-NPN	Sw,Pow,65V,2A,20W	49a$	Sca,Sem,Ssi	2N5002,2N5004,2N5284..85
2N3139	Si-NPN	Sw,Pow,140V,2A,20W	49a$	Sca,Sem,Ssi	-
2N314	Ge-NPN	=2N313:8MHz	2a	Gen	-
2N3140	Si-NPN	Sw,Pow,65V,2A,20W	49a$	Sca,Sem,Ssi	2N5002,2N5004,2N5284..85
2N3141	Si-NPN	Sw,Pow,140V,2A,20W	49a$	Sca,Sem,Ssi	-
2N3142	Si-NPN	Sw,Pow,65V,2A,20W	49a	Sca,Sem,Ssi	2N5002,2N5004,2N5284..85
2N3143	Si-NPN	Sw,Pow,140V,2A,20W	49a	-	-
2N3144	Si-NPN	Sw,Pow,65V,2A,20W	49a	-	2N5002,2N5004,2N5284..85
2N3145	Si-NPN	Sw,Pow,140V,2A,20W	49a	-	-
2N3146	Ge-PNP	Sw,Pow,150V,15A,150W	23a$	Csr,Gpd,Sty	-
2N3147	Ge-PNP	=2N3146:180V	23a$	Csr,Gpd,Sty	-
2N3148	Ge-PNP	Sw,11V,0,05A,0,025W,>25MHz	37d	Spr	ASZ21,2N705,2N960..967,2N2955..57
2N3149	Si-NPN	Sw,Pow,80/80V,70A,300W	49a$	USA	2N9309..11
2N315	Ge-PNP	Sw,20V,Ueb=20V,0,2A,0,1W,5MHz	2a	USA	2N1305
2N3150	Si-NPN	=2N3149:100/100V	49a$	USA	2N9309..11
2N3151	Si-NPN	=2N3149:150/150V	49a$	USA	-
2N3152	Si-NPN	Sw,120V,0,1A,2,5W(Tc=100°),>200MHz	49a	Sca,Spe,Sty	-
2N3153	Si-NPN	Chopper,15/15/15V,0,1A,0,3W,>30MHz	2a$	Idt,Tdy	-
2N3154	Ge-PNP	Sw,Pow,40V,3A,38W,B>60	-	Gpd,Stc	-
2N3155	Ge-PNP	=2N3154:60V	-		-
2N3156	Ge-PNP	=2N3154:80V	-		-
2N3157	Ge-PNP	=2N3154:100V	-		-
2N3158	Ge-PNP	=2N3154:B>30	-		-
2N3159	Ge-PNP	=2N3154:60V,B>30	-		-
2N315A,B	Ge-PNP	=2N315:30V,0,15W	2a	-	2N1305
2N316	Ge-PNP	Sw,20V,Ueb=20V,0,2A,0,1W,12MHz	2a	USA	2N1307
2N3160	Ge-PNP	=2N3154:80V,B>30	-		-
2N3161	Ge-PNP	=2N3154:100V,B>30	-		-
2N3162	Si-NPN	GenP,45V,0,3W,B>50	5	Fch,Sty	-
2N3163	Si-PNP	Sw,Pow,40V,3A,85W	49a$	Sca,Ssi	2N5003,2N5005,2N5286..87
2N3164	Si-PNP	=2N3163:60V	49a$	-	2N5003,2N5005,2N5286..87
2N3165	Si-PNP	=2N3163:80V	49a$	-	2N5003,2N5005,2N5286..87
2N3166	Si-PNP	=2N3163:100V	49a$	-	2N5003,2N5005,2N5286..87
2N3167	Si-PNP	=2N3163:	-		(BD246,BDV92,2SB688,2SB775..776,..)
2N3168	Si-PNP	=2N3163:60V	-		(BD246A,BDV94,2SB688,2SB775..776..)
2N3169	Si-PNP	=2N3163:80V	-		(BD246B,BDV94,2SB688,2SB775..776..)
2N316A	Ge-PNP	=2N316:30V,0,15A	2a	-	2N1307
2N317	Ge-PNP	Sw,20V,Ueb=20V,0,2A,0,1W,20MHz	2a	USA	2N1309
2N3170	Si-PNP	=2N3163:100V	-		(BD246C,BDV96,2SB688,2SB775..776..)
2N3171	Si-PNP	=2N3163:75W	23a$	USA	BD246,BDV92,BDW52C,BDX92,2SA980..
2N3172	Si-PNP	=2N3163:60V,75W	23a$	-	BD246A,BDV92,BDX92,2SA980,BDW52C...
2N3173	Si-PNP	=2N3163:80V,75W	23a$	-	2SA980,BD246B,BDV94,BDX94...
2N3174	Si-PNP	=2N3163:100V,75W	23a$	-	BD246C,BDV96,BDX96,2SA980..
2N3175	Si-PNP	Sw,Pow,40V,5A,85W	49a$	Sca,Ssi	2N5003,2N5005,2N5286..87
2N3176	Si-PNP	=2N3175:60V	49a$	-	2N5003,2N5005,2N5286..87
2N3177	Si-PNP	=2N3175:80V	49a$	-	2N5003,2N5005,2N5286..87
2N3178	Si-PNP	=2N3175:100V	49a$	-	2N5003,2N5005,2N5286..87
2N3179	Si-PNP	=2N3175:	-		(BD246,BDV92,2SB688,2SB775..776,..)
2N317A	Ge-PNP	=2N317:25V,0,15W	2a	-	2N1309
2N318	Opto	-	-		-
2N3180	Si-PNP	=2N3175:60V	-		(BD246A,BDV92,2SB688,2SB775..776..)
2N3181	Si-PNP	=2N3175:80V	-		(BD246B,BDV94,2SB688,2SB775..776..)
2N3182	Si-PNP	=2N3175:100V	-		(BD246C,BDV96,2SB688,2SB775..776..)
2N3183	Si-PNP	=2N3175:75W	23a$	USA	2SA980,BD246,BDV92,BDX92...
2N3184	Si-PNP	=2N3175:60V,75W	23a$	-	BD246A,BDV92,BDX92,2SA980..
2N3185	Si-PNP	=2N3175:80V,75W	23a$	-	2SA980,BD246B,BDV94,BDW52C,BDX94...
2N3186	Si-PNP	=2N3175:100V,75W	23a$	-	2SA980,BD246C,BDV96,BDX96,TIP2955...

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2N3187	Si-PNP	Sw,Pow,40V,5A,85W	49a$	Sca,Ssi	2N5003,2N5005,2B5286..87
2N3188	Si-PNP	=2N3187:60V	49a$	-	2N5003,2N5005,2B5286..87
2N3189	Si-PNP	=2N3187:80V	49a$	-	2N5003,2N5005,2B5286..87
2N319	Ge-PNP	AF-Driver,25V,0,5A,0,225W,B>25,>1MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3190	Si-PNP	=2N3187:100V	49a$	-	2N5003,2N5005,2B5286..87
2N3191	Si-PNP	=2N3187:	-		(BD246,BDV92,2SB688,2SB775..776,..)
2N3192	Si-PNP	=2N3187:60V	-		(BD246A,BDV92,2SB688,2SB775..776..)
2N3193	Si-PNP	=2N3187:80V	-		(BD246B,BDV94,2SB688,2SB775..776..)
2N3194	Si-PNP	=2N3187:100V	-		(BD246C,BDV96,2SB688,2SB775..776..)
2N3195	Si-PNP	=2N3187:75W	23a$	USA	2SA980,BD246,BDV92,BDW52C,BDX92...
2N3196	Si-PNP	=2N3187:60V,75W	23a$	-	2SA980,BD246A,BDV92,BDW52C,BDX92...
2N3197	Si-PNP	=2N3187:80V,75W	23a$	-	BD246B,BDV94,BDX94,2SA980..
2N3198	Si-PNP	=2N3187:100V,75W	23a$	-	2SA980,BD246C,BDV96,BDX96,MJ2955...
2N3199	Si-PNP	Sw,Pow,40V,3A,40W	49a$	Ssi,Tra	2N5003,2N5005,2N5286..87
2N32(A)	Ge-PNP	Sw,40V,Ueb=40V,8mA,0,05W,2,7MHz	?1a	Rca	(AC125..126,AC151,ASY48)
2N320	Ge-PNP	=2N319:B>34,>1,5MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3200	Si-PNP	=2N3199:60V	49a$	-	2N5003,2N5005,2N5286..87
2N3201	Si-PNP	=2N3199:80V	49a$	-	2N5003,2N5005,2N5286..87
2N3202	Si-PNP	=2N3199:8,7W(Tc=25°)	2a$	Ssi,Tra,++	BSS44,BSS46,BUY90,2N6190..93
2N3203	Si-PNP	=2N3199:60V,8,7W(Tc=25°)	2a$	-	BSS44,BSS46,BUY90,2N6190..93
2N3204	Si-PNP	=2N3199:80V,8,7W(Tc=25°)	2a$	-	BSS46,BUY90,2N6190..93
2N3205	Si-PNP	Sw,Pow,40V,2A,40W	49a$	Sca,Ssi,Tra	2N5003,2N5005,2N5286..87
2N3206	Si-PNP	=2N3205:60V	49a$	-	2N5003,2N5005,2N5286..87
2N3207	Si-PNP	=2N3205:100V	49a$	-	2N5003,2N5005,2N5286..87
2N3208	Si-PNP	AF,Sw,40V,2A,8,7W(Tc=25°)	2a$	USA	BSS46,BUY90,2N6190..93
2N3209	Si-PNP	Sw,20V,0,2A,0,36W,<60/90nS	2a$	USA,Sgs,Tix	BSW24,BSX36,2N4125..26
2N321	Ge-PNP	=2N319:B>53,>2MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3210	Si-NPN	Sw,40V,0,5A,0,36W,<40/40nS	2a$	USA,Mot	BSS10,BSX26,BSX39,2N3261
2N3211	Si-NPN	Sw,40V,0,5A,0,36W,<40/40nS	2a$	USA,Mot	BSS10,BSX26,BSX39,2N3261
2N3212	Ge-PNP	AF,Sw-Pow,100V,5A,14W	43a$	Del,Gpd,Stc	-
2N3213	Ge-PNP	=2N3212:80V	43a$	-	-
2N3214	Ge-PNP	=2N3212:60V	43a$	-	-
2N3215	Ge-PNP	=2N3212:40V	43a$	-	-
2N3216	Ge-PNP	AF,Sw,20/10/20V,0,5A,0,15W,>9MHz	2a	Cen,Stc	(ASY76..77,2N1189..90)
2N3217	Si-PNP	Chopper,15/10/15V,0,1A,0,4W	2a$	USA	2N2944
2N3218	Si-PNP	Chopper,25/20/25V,0,1A,0,4W	2a$	USA	2N2945
2N3219	Si-PNP	Chopper,40/35/40V,0,1A,0,4W	2a$	USA	2N2946
2N322	Ge-PNP	AF-Driver,18V,0,5A,0,225W,B>34,>1MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3220	Si-NPN	Sw,Pow,100V,2A,>10MHz,B>20	49a	USA	2N5002,2N5004,2N5284..85
2N3221	Si-NPN	=2N3220:B>40	49a	-	2N5002,2N5004,2N5284..85
2N3222	Si-NPN	=2N3220:80V	49a	-	2N5002,2N5004,2N5284..85
2N3223	Si-NPN	=2N3220:80V,B>40	49a	-	2N5002,2N5004,2N5284..85
2N3224	Si-PNP	AF-Driver,100V,0,7W,>60MHz,a>20	2a$	USA	BSW40,2N3634..37,2SA606,2SA712
2N3225	Si-PNP	=2N3224:>80MHz,a>40	2a$	USA	BSW40,2N3634..37,2SA606,2SA712
2N3226	Si-NPN	AF-Pow,35V,5A,75W	23a$	Sca,Sol,Ssi	BD245,BDV91,BDX91,2N4914..15..
2N3227	Si-NPN	Fast-Sw,40V,0,5A,0,36W,<23/28nS	2a$	USA,Mot,Tix	BSS10,BSX26,BSX39,2N3261
2N3228	Thy-50Hz	200V,3,2A(Tc=75°),Igt/Ih<15/<20mA	22a$	Rca,Sgs,Tag	2N3525,2N4101,BStC0513L,TAG671-200
2N3229	Si-NPN	VHF-Pow,105V,2,5A,Pq>15W(150MHz)	49a	Fer,Rca,Ssi	-
2N323	Ge-PNP	=2N322:B>53,>1,5MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3230	Si-NPN-Darl	Sw,Pow,80V,7A,25W,B>1000	-	Fer,Rca,Tsc	-
2N3231	Si-NPN-Darl	=2N3230:100V	-	Fer,Rca,Tsc	-
2N3232	Si-NPN	AF,Sw-Pow,60V,7,5A,117W	23a$	USA,Mot	BD245A,BD311,BDV91,BDW51C,BDX91...
2N3233	Si-NPN	=2N3232:100V	23a$	USA,Mot	2N5632..34,BD245C,BDV95,BDW51C,BDX95...
2N3234	Si-NPN	=2N3232:160V	23a$	USA,Mot	BD245D,BDX11,2N3442,2SC2260..62..
2N3235	Si-NPN	AF,Sw-Pow,55V,15A,117W	23a$	USA	2N3055,BD315,BD545A,BD745A...
2N3236	Si-NPN	AF,Sw-Pow,90V,15A,150W	23a$	USA	2N3772,2N5629..31,BD317,BD745C,BDW51C...
2N3237	Si-NPN	AF,Sw-Pow,90V,20A,200W	23a$	USA	BDY29,MJ802,2N3772,2SD797
2N3238	Si-NPN	AF,Sw-Pow,80V,15A,150W	23a$	USA,Mot	2N3772,BD315,BD545B,BD745B,BDW51C...
2N3239	Si-NPN	AF,Sw-Pow,80V,15A,150W	23a$	USA,Mot	2N3772,BD315,BD545B,BD745B,BDW51C...
2N324	Ge-PNP	=2N322:B>72,>2MHz	2a&	USA,Gen,Mot	AC128,AC153,AC188
2N3240	Si-NPN	AF,Sw-Pow,160V,15A,150W	23a$	USA,Mot	2N3773,2SD752,BD745F,BDW12,BUX10...
2N3241	Si-NPN	GenP,30V,0,1A,0,5W,>50MHz,B>70	2a$	USA	BC168,BC183,BC238,BC548..
2N3241A	Si-NPN	=2N3241:0,2A,a>100	2a$	-	BC168,BC183,BC238,BC548..
2N3242	Si-NPN	GenP,30V,0,2A,0,5W,>50MHz,B>100	2a$	USA	BC168,BC183,BC238,BC548..

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2N3242A	Si-NPN	=2N3242: 40V,0,3A, a>125	2a$	-	BC167,BC182,BC237,BC547..
2N3244(S)	Si-PNP	Sw, 40V, 1A, 1W, <50/185nS	2a$	USA,Mot,Tix	2N3467..68,2SA717,2SA799
2N3245(S)	Si-PNP	Sw, 50V, 1A, 1W, <55/165nS	2a$	USA,Mot,Tix	2N3468,2SA717,2SA799
2N3246	Si-NPN	GenP, 60V,0,05A,0,35W, >60MHz	2a$	USA,Nsc	BC174,BC182,BC190,BC546..
2N3247	Si-NPN	=2N3246: Min,0,15W	??c	Upi	-
2N3248	Si-PNP	Sw, 15V,0,2A,0,36W, >250MHz, <20/80nS	2a$	USA,Mot,Nsc	BSX36
2N3249	Si-PNP	=2N3248: >300MHz	2a$	USA,Mot,Nsc	BSX36
2N325	Ge-PNP	Sw, Pow, 35V, 2A, 12W	23a$	Sylvania	AD149,AUY19..20,2N2137..46..
2N3250	Si-PNP	Sw, 50V,0,2A,0,36W, <70/225ns	2a$	Fch,Mot,Nsc	BSW24,2N2906..07(A)
2N3250A	Si-PNP	=2N3250: 60V	2a$	-	BSW24,2N2906..07(A)
2N3251	Si-PNP	Sw, 50V,0,2A,0,36W, <70/250nS	2a$	Fch,Mot,Nsc	BSW24,2N2906..07(A)
2N3251A	Si-PNP	=2N3251: 60V	2a$	-	BSW24,2N2906..07(A)
2N3252(S)	Si-NPN	Sw, 60V, 1A, 1W, <45/70ns	2a$	Fch,Mot,Nsc	BSS27,BSV77,BSV95,2N5189..
2N3253(S)	Si-NPN	Sw, 75V, 1A, 1W, <50/70nS	2a$	=2N3253	BSV95,2N3735,2SC1069
2N3254	Thy-Fast	15V,0,2SA(Ta=55°C), Igt/Ih<0,02/<2mA	2a$	Mot,Ssi,Uni	(2N2322A)
2N3255	Thy-Fast	=2N3254: 30V	2a$	-	(2N2323A)
2N3256	Thy-Fast	=2N3254: 60V	2a$	-	(2N2324A)
2N3257	Thy-Fast	=2N3254: Igt/Ih<0,2/<3mA	2a$	-	BRY58/30,TAG06Y,2N6605,(2N2322,TIC44)
2N3258	Thy-Fast	=2N3255: Igt/Ih<0,2/<3mA	2a$	-	BRY58/30,TAG06Y,2N6605,(2N2323,TIC44)
2N3259	Thy-Fast	=2N3256: Igt/Ih<0,2/<3mA	2a$	-	BRY58/60,TAG06YY,2N6606S,(TIC46)
2N326	Ge-NPN	AF, Sw-Pow, 35V, 2A, 7W	23a$	USA	2N1218
2N3260	Si-NPN	Sw, Pow, 200/200V, 30A, 200W	49a$	Idi,Stc	2N6324..25
2N3261	Si-NPN	Fast-Sw, 40V,0,5A,0,3W, <13/16nS	2a$	USA,Fer	BSS10,BSX26,BSX39
2N3262	Si-NPN	Sw, 100V, 1,5A, 1W, <40/750nS	2a$	USA,Fer,Tix	2SD854
2N3263	Si-NPN	Sw, Pow, 150V, 25A, 84W, >20MHz	-	USA,Rca	-
2N3264	Si-NPN	=2N3263: 120V	-	USA,Rca	-
2N3265	Si-NPN	=2N3263: 125W	49a$	USA,Rca,Tix	2N2817..18,2N2821..22
2N3266	Si-NPN	=2N3263: 120V, 125W	49a$	USA,Rca,Tix	2N2817..18,2N2821..22,2N5539
2N3267	Ge-PNP	UHF, 15V,0,02A,0,075W, >900MHz	5g	Ssi	AF139,AF239(S),2N3283..86
2N3268	Si-NPN	GenP, 45V,0,025A,0,15W, >2,5MHz	2a	USA	BC167,BC182,BC237,BC547..
2N327(A,B)	Si-PNP	GenP,-/40V,Ueb=20V,0,05A,0,337W,A: 50V,0,386W,B: 50V,0,1A,0,4W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N3273	Thy-50Hz	100V,2,2A(Tc=85°), Igt/Ih<0,2/<2mA	2a$	Ssi,Uni	(TAG106A,C106A1,X0403A,TAG108A)
2N3274	Thy-50Hz	=2N3273: 200V	2a$	-	(TAG106B,C106B1,X0403B,TAG108B)
2N3275	Thy-50Hz	=2N3273: 300V	2a$	-	(TAG106C,C106C1,X0403C,TAG108C)
2N3276	Thy-50Hz	=2N3273: 400V	2a$	-	(TAG106D,C106D1,X0403D,TAG108D)
2N3277	P-FET	GenP, 25V, Idss>0,15mA, Up<5V	5g+	Fch,Isi,Sol	2N5473..74,2N5797
2N3278	P-FET	GenP, 25V, Idss>0,4mA, Up<8V	5g+	Fch,Isi,Sol	BF320A,2N3809,2N3820,2N5475
2N3279	Ge-PNP	VHF-Pre/Mix/Osc, LN, 30V,0,05A, 500MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N328(A,B)	Si-PNP	GenP,-/30V,Ueb=20V,0,05A,0,337W,A: 50V,0,386W,B: 50V,0,1A,0,4W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N3280	Ge-PNP	VHF-Pre/Mix/Osc, LN, 30V,0,05A, 500MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3281	Ge-PNP	VHF-Pre/Mix/Osc, LN, 30V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3282	Ge-PNP	VHF-Pre/Mix/Osc, LN, 30V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3283	Ge-PNP	VHF-Pre/Mix/Osc, LN, 25V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3284	Ge-PNP	VHF-Pre/Mix/Osc, LN, 25V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3285	Ge-PNP	VHF-Pre/Mix/Osc, LN, 20V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3286	Ge-PNP	VHF-Pre/Mix/Osc, LN, 20V,0,05A, 400MHz	5g	Mot,Ssi,Sty	AF139,AF239(S)
2N3287	Si-NPN	VHF-Pre/Mix/Osc, 40V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3288	Si-NPN	VHF-Pre/Mix/Osc, 40V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3289	Si-NPN	VHF-Pre/Mix/Osc, 30V,0,05A, 500MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N329(A,B)	Si-PNP	GenP,-/20V,Ueb=20V,0,05A,0,337W,A: 50V,0,386W,B: 50V,0,1A,0,4W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N3290	Si-NPN	VHF-Pre/Mix/Osc, 30V,0,05A, 500MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3291	Si-NPN	VHF-Pre/Mix/Osc, 25V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3292	Si-NPN	VHF-Pre/Mix/Osc, 25V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3293	Si-NPN	VHF-Pre/Mix/Osc, 20V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3294	Si-NPN	VHF-Pre/Mix/Osc, 20V,0,05A, 600MHz	5g	Mot,Sca,Ssi	BF310,BF314,BFS02,BFS05,BFS07..
2N3295(S)	Si-NPN	HF-Dr, 60V,0,2SA, Pep=0,3W(30MHz)	2a$	Mot,Sca,Ssi	MRF402,MRF8003
2N3296	Si-NPN	HF-Dr/Out, 60V,0,7A, Pep=3W(30MHz)	49a$	Mot,Sca,Ssi	-
2N3297	Si-NPN	HF-Pow, 60V, 1,5A, Pep=12W(30MHz)	23a$	Mot,Sca,Ssi	-
2N3298	Si-NPN	HF-Osc/Dr, 25V,0,1A, Pq>0,06W(80MHz)	2a$	Mot,Sca,Ssi	BFX59
2N3299(S)	Si-NPN	Sw, 60V,0,5A,0,8W, <60/150nS, B>40	2a$	USA,EUR	BSS27,BSV77,BSV95,2N5189..
2N33	Ge-PNP	HF, 8,5V, 7mA, 0,03W, 3MHz	?1a	Rca	AF124..127,AF200
2N330	Si-PNP	GenP,-/20V,Ueb=20V,0,05A,0,337W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N3300(S)	Si-NPN	=2N3299: B>100	2a$	USA,EUR	BSS27,BSV77,BSV95,2N5189..
2N3301	Si-NPN	=2N3299: 0,36W	2a$	USA,EUR	BSS26,BSV59,BSX49,2N4014..

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2N3302	Si-NPN	=2N3299:0,36W,B>100	2a$	USA,EUR	BSS26,BSV59,BSX49,2N4014..
2N3303	Si-NPN	Sw,Dr,25V,1A,0,6W,>450MHz,<15/25nS	2a$	USA,EUR	BSS28..29,BSV69,2N3724A,2N5189..
2N3304	Si-PNP	Sw,6V,0,1A,0,3W,>500MHz,<60/60nS	2a$	USA,Mot,Tix	BSX36
2N3305	Si-PNP	GenP,50V,0,6W,>20MHz,B>40	2a$	USA	BC161,BC303..304,BSW23,2N2303..
2N3306	Si-PNP	=2N3305:B>100	2a$	USA	BC161,BC303..304,BSW23,2N2303..
2N3307	Si-PNP	VHF-Pre/Mix/Osc,40V,0,05A,0,2W,>300MHz	5g	USA,Mot	BF324,BF414,BFS06,BF914,BF936..
2N3308	Si-PNP	VHF-Pre/Mix/Osc,30V,0,05A,0,2W,>300MHz	5g	USA,Mot	BF324,BF414,BFS06,BF914,BF936..
2N3309	Si-NPN	VHF-Dr/Out,50V,0,5A,Pq>2W(250MHz)	2a$	Mot,Tho,Tix	BFS23,BLY34,2SC2419
2N3309A	Si-NPN	=2N3309:60V,Pq>2,2W(250MHz)	2a$	Mot	BFS23,BLY34,2SC2419
2N3310A	Si-PNP	GenP,-/50V,Ueb=50V,0,05A,0,386W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N3308	Si-PNP	GenP,-/50V,Ueb=50V,0,1A,0,4W	2a	USA	(BC212,BC257,BC307,BC557,++)
2N331	Ge-PNP	AF-Driver,30V,Ueb=12V,0,2W,>0,4MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N3310	Si-NPN	VHF-Dr/Out,35V,0,2A,0,3W,>300MHz	?2a	Mot,Sty	BFR36,BFR98,BFX55,MRF607..
2N3311	Ge-PNP	Sw,Pow,30V,5A,170W,B>60	38a$	USA,Mot	2N1980..82,2N2075..82,2N2491..93
2N3312	Ge-PNP	=2N3311:45V	38a$	USA,Mot	2N1980..82,2N2075..82,2N2491..93
2N3313	Ge-PNP	=2N3311:60V	38a$	USA,Mot	2N1981..82,2N2079..80,2N2491..93
2N3314	Ge-PNP	=2N3311:B>100	38a$	USA,Mot	2N1980..82,2N2075..82,2N2491..93
2N3315	Ge-PNP	=2N3311:45V,B>100	38a$	USA,Mot	2N1980..82,2N2075..82,2N2491..93
2N3316	Ge-PNP	=2N3311:60V,B>100	38a$	USA,Mot	2N1981..82,2N2079..80,2N2491..93
2N3317	Si-PNP	Chopper,30/30/30V,0,05A,0,15W	2a	Sem,Tdy,Upi	2N2946
2N3318	Si-PNP	Chopper,15/15/15V,0,05A,0,15W	2a	Sem,Tdy,Upi	2N2945
2N3319	Si-PNP	Chopper,10/6/10V,0,05A,0,15W	2a	Sem,Tdy,Upi	2N2944
2N332	Si-NPN	GenP,45V,25mA,0,15W,4MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N332(A)	Si-NPN	A:0,5W,10MHz	-		-
2N3320	Ge-PNP	Sw,15V,0,1A,0,06W,<20/35nS	2a	Idi,Ssi,Upi	2N705,2N960..67,2N2955..57
2N3321	Ge-PNP	Sw,12V,0,1A,0,06W,<20/40nS	2a	Idi,Ssi,Upi	2N705,2N960..67,2N2955..57
2N3322	Ge-PNP	Sw,12V,0,1A,0,06W,<20/45nS	2a	Idi,Ssi,Upi	2N705,2N960..67,2N2955..57
2N3323	Ge-PNP	AM/FM,35V,0,1A,0,15W,>200MHz	2a$	USA,Mot	AF109R,AF139,AF239(S),2N3283..86
2N3324	Ge-PNP	AM/FM,35V,0,1A,0,15W,>200MHz	2a$	USA,Mot	AF109R,AF139,AF239(S),2N3283..86
2N3325	Ge-PNP	AM/FM,35V,0,1A,0,15W,>200MHz	2a$	USA,Mot	AF109R,AF139,AF239(S),2N3283..86
2N3326	Si-NPN	Sw,60V,0,8A,0,8W,>250MHz	2a$	USA,Fch,Itt	BSW51..54,BSX32,2N2218..19(A)..
2N3327	Si-NPN	HF-Pow,65V,2A,20W,>100MHz	49a	Sca,Ssi	BLY59,2N3375
2N3328	P-FET	GenP,20V,Idss<1mA,Up<6V	5g+	Isi,Six,Tix	J176
2N3329	P-FET	=2N2497:	5g+	USA,Mot,Tix	2N2497,J176
2N3333(A)	Si-NPN	GenP,45V,25mA,0,15W,5MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N3330	P-FET	=2N2498:	5g+	USA,Mot,Tix	2N2498,J176
2N3331	P-FET	=2N2499:	5g+	USA,Mot,Tix	2N2499,J176
2N3332	P-FET	=2N2500:	5g+	USA,Mot,Tix	2N2500,J176
2N3333	P-FET	Dual,20V,Idss<1mA,Up<1,6V	10-FLP/cl	TI	-
2N3334	P-FET	Dual,20V,Idss<1mA,Up<1,6V	10-FLP/cl	TI	-
2N3335	P-FET	Dual,20V,Idss<1mA,Up<1,6V	10-FLP/cl	TI	-
2N3336	P-FET	Dual,20V,Idss<1mA,Up<1,6V	10-FLP/cl	TI	-
2N3337	Si-NPN	HF/AF,40V,0,05A,0,3W,>400MHz	5g	Fch,Sgs,++	BF198..199,BF224..225,BF596..597,..
2N3338	Si-NPN	HF/AF,40V,0,05A,0,3W,>400MHz	5g	Fch,Sgs,++	BF198..199,BF224..225,BF596..597,..
2N3339	Si-NPN	HF/AF,40V,0,05A,0,3W,>400MHz	5g	Fch,Sgs,++	BF198..199,BF224..225,BF596..597,..
2N333A	Si-NPN	GenP,45V,25mA,0,5W,11MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N334(A,B)	Si-NPN	GenP,45V,25mA,0,15,8MHz,A:0,5W,12MHz,B:60V,0,5W,12MHz..	2a	USA	BC167,BC182,BC237,BC547,+
2N3340	Si-NPN	GenP,30V,0,03A,0,4W,>70MHz	2a$	USA	BC168,BC183,BC238,BC548..
2N3341	Si-PNP	GenP,30V,0,03A,0,4W,>50MHz	2a$	USA	BC213,BC258,BC308,BC558..
2N3342	Si-PNP	Chopper,20/8/20V,0,05A,0,25W	2a	USA	2N2944
2N3343	Si-PNP	Chopper,25/8/25V,0,05A,0,25W	2a	USA	2N2944
2N3344	Si-PNP	Chopper,30/30/30,0,05A,0,25W	2a	USA	2N2946
2N3345	Si-PNP	Chopper,50/50/50,0,05A,0,25W	2a	USA	2N2946
2N3346	Si-PNP	Chopper,50/50/50,0,05A,0,25W	2a	USA	2N2946
2N3347	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	Mic,Nsc,Ray	BFX36,2N3806..11,2N4015..16
2N3348	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	=2N3347	BFX36,2N3806..11,2N4015..16
2N3349	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	=2N3347	BFX36,2N3806..11,2N4015..16
2N335(A,B)	Si-NPN	GenP,45V,25mA,0,15W,7MHz,A:0,5W,13MHz,B:60V,0,5W	2a	USA	BC167,BC182,BC237,BC547,+
2N3350	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	=2N3347	BFX36,2N3806..11,2N4015..16
2N3351	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	=2N3347	BFX36,2N3806..11,2N4015..16
2N3352	Si-PNP	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	=2N3347	BFX36,2N3806..11,2N4015..16
2N336	Si-NPN	GenP,45V,25mA,0,15W,7MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N3365	N-FET	GenP,LN,40V,Idss>0,8mA,Up<12V	2b&	USA,Mot,Tix	2N4340
2N3366	N-FET	GenP,LN,40V,Idss>0,2mA,Up<7V	2b&	USA,Mot,Tix	2N4119,2N4338

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2N3367	N-FET	GenP,LN,40V,Idss>0,05mA,Up<2,5V	2b&	USA,Mot,Tix	2N4118,2N4338
2N3368	N-FET	GenP,LN,40V,Idss>2mA,Up<12V	2b&	USA,Mot,Tix	2N4341,2SK113
2N3369	N-FET	GenP,LN,40V,Idss>0,5mA,Up<12V	2b&	USA,Mot,Tix	2N4339
2N336A	Si-NPN	GenP,45V,25mA,0,5W,15MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N337	Si-NPN	GenP,45V,20mA,0,125W,20MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N3370	N-FET	GenP,LN,40V,Idss>0,1mA,Up<3,2V	2b&	USA,Mot,Tix	2N4118,2N4340
2N3371	Ge-PNP	VHF,LN,25V,0,1A,0,15W,>400MHz	2a$	Idi,Spe,Tix	AF139,AF239(S),2N3283..86
2N3374	Si-NPN	HF/Sw,80V,0,5A,Pq=2,8W(130MHz)	2a$	Sty	BFS23,BLY34,2SC2419
2N3375	Si-NPN	VHF/UHF-Pow,65V,1,5A,Pq>3W(400MHz)	49a	USA,EUR	-
2N3376	P-FET	GenP,30V,Idss>0,6mA,Up<5V	5g+	Nsc,Six,++	J201
2N3377	P-FET	=2N3376:	?24	Nsc,Six,++	-
2N3378	P-FET	GenP,30V,Idss>3mA,Up<5V	5g+	Nsc,Six,++	J177
2N3379	P-FET	=2N3378:	?24	Nsc,Six,++	-
2N337A	Si-NPN	GenP,45V,20mA,0,5W,30MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N338	Si-NPN	GenP,45V,20A,0,125W,30MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N3380	P-FET	GenP,30V,Idss>3mA,Up<9,5V	5g+	Nsc,Six,++	J176
2N3381	P-FET	=2N3380:	?24	Nsc,Six,++	-
2N3382	P-FET	GenP,30V,Idss>3mA,Up<5V	5g+	Nsc,Six,++	J176
2N3383	P-FET	=2N3382:	?24	Nsc,Six,++	-
2N3384	P-FET	GenP,30V,Idss>15mA,Up<5V	5g+	Nsc,Six,++	J175
2N3385	P-FET	=2N3384:	?24	Nsc,Six,++	-
2N3386	P-FET	GenP,30V,Idss>15mA,Up<9,5V	5g+	Nsc,Six,++	2N5116
2N3387	P-FET	=2N3386:	?24	Nsc,Six,++	-
2N3388	Si-NPN	Nix,Sw,125V,2,5mA,0,6W,>36MHz	2a$	Ssi,Stc,Tra	BF257..259,BF657..659,2N5058..59..
2N3389	Si-NPN	Nix,Sw,195V,7mA,0,6W,>36MHz	2a$	Ssi,Stc,Tra	BF258..259,BF658..659,2N5058..59..
2N338A	Si-NPN	GenP,45V,20A,0,5W,45MHz	2a	USA	BC167,BC182,BC237,BC547,+
2N339(A)	Si-NPN	AF,55V,A:60V,0,15A,0,25W,>10MHz	2a	USA	BC174,BC190,BC546,2SC3245(A)..
2N3390	Si-NPN	GenP,25V,0,1A,0,36W,140MHz,B>400	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3391(A)	Si-NPN	=2N3390:160MHz,B>250	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3392	Si-NPN	=2N3390:>120MHz,B>150	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3393	Si-NPN	=2N3390:>120MHz,B>90	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3394	Si-NPN	=2N3390:>120MHz,B>55	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3395	Si-NPN	=2N3390:B>150	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3396	Si-NPN	=2N3390:B>90	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3397	Si-NPN	=2N3390:B>55	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3398	Si-NPN	=2N3390:B>55	7c	USA,Mic,Tho	BC168,BC183,BC238,BC548..
2N3399	Ge-PNP	UHF,20V,7mA,0,08W,>400MHz	5g	Amp,Ssi,Sty	AF139,AF239(S),2N3283..86
2N34(A)	Ge-PNP	AF,Sw,25V,8mA,0,05W,0,6MHz	?1a	USA	(AC125..126,AC151,ASY26..27)
2N34/5	Ge-PNP	AF,Sw,40V,0,1A,0,15W,0,8MHz	2a	Syl	(AC125..126,AC151,ASY48)
2N340(A)	Si-NPN	AF,85V,A:BSV,0,15A,0,25W,>10MHz	2a	USA	BC546,2SC2240,2SC2459,2SC3245(A)..
2N3400	Ge-PNP	Sw,20V,0,1A,0,15W,<90/260nS	2a	Cen,Sty	2N2635,2N2955..57
2N3401	Si-PNP	Chopper,25/25/25V,0,1A,0,25W	2a	Tdy	2N2945
2N3402	Si-NPN	GenP,25V,0,5A,0,56W,B>75	7co	USA,Mic,Tho	BC337..338,BC635,BC637,BC639..
2N3403	Si-NPN	=2N3402:B>180	7co	USA,Mic,Tho	BC337..338,BC635,BC637,BC639..
2N3404	Si-NPN	=2N3402:50V	7co	USA,Mic,Tho	BC337,BC637,BC639,2SD667..
2N3405	Si-NPN	=2N3402:50V,B>180	7co	USA,Mic,Tho	BC337,BC637,BC639,2SD667..
2N3406	UJT-P	Iv>8mA	5	Gen	-
2N3407	Si-NPN	HF,35V,0,1A,0,2W,>300MHz	5g	Mot,Sty	BF198..199,BF224..225,BF596..597,..
2N3408	Si-PNP	HF-Dr/Out,40V,0,5A,4W,>200MHz	49a	Mot,Sty	-
2N3409	Si-NPN	Dual,LN,60V,0,5A,0,6W,>250MHz	81bs	Mot,Sgs,++	-
2N341(A)	Si-NPN	AF,125V,A:125V,0,15A,0,25W,>10MHz	2a	USA	BF257,2SC2240,2SC2459,2SC3245(A)..
2N3410	Si-NPN	Dual,LN,60V,0,5A,0,6W,>250MHz	81bs	Mot,Sgs,++	-
2N3411	Si-NPN	Dual,LN,60V,0,5A,0,6W,>250MHz	81bs	Mot,Sgs,++	-
2N3412	Ge-PNP	HF,20V,0,1A,0,06W,>100MHz	2a	Csr,Etc,Idi	2N3283..86,(AF106,AF109R,AF306)
2N3413	Ge-PNP	Sw,Chopper,150/150/150V,0,2A(ss)	2a	Sca,Sty	-
2N3414	Si-NPN	=2N3402:0,36W	7c	USA,Mic,Tho	→2N3402
2N3415	Si-NPN	=2N3403:0,36W	7c	USA,Mic,Tho	→2N3403
2N3416	Si-NPN	=2N3404:0,36W	7c	USA,Mic,Tho	→2N3404
2N3417	Si-NPN	=2N3405:0,36W	7c	USA,Mic,Tho	→2N3405
2N3418	Si-NPN	AF,Sw,85V,5A,15W(Tc=100°),B>20	2a$	USA,Sgs,Tix	BUX34,BUY80,2N5336..39
2N3419	Si-NPN	=2N3418:125V	2a$	USA,Sgs,Tix	2N4895..97,2N5339,BUX34,BUY80...
2N342(A,B)	Si-NPN	AF,60V,>8MHz,A,B:85V,60mA	2a*	USA	BC546,2SC2240,2SC2459,2SC3245(A)..
2N3420	Si-NPN	=2N3418:B>40	2a$	USA,Sgs,Tix	BUX34,BUY80,2N5336..39
2N3421	Si-NPN	=2N3418:125V,B>40	2a$	USA,Sgs,Tix	2N4895..97,2N5339,BUX34,BUY80...

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2N3423	Si-NPN	Dual,30V,0,05A,0,45W,>600MHz	81bs	USA,Mot,Sgs	BFY84
2N3424	Si-NPN	Dual,30V,0,05A,0,45W,>600MHz	81bs	USA,Mot,Sgs	BFY84
2N3425	Si-NPN	Dual,40V,0,4W,>300MHz	81bs	Fch,Mot,Ray	-
2N3426	Si-NPN	Sw,25V,1A,0,6W,>450MHz,<15/25nS	2a$	USA,Phi,Sgs	BSS28..29,BSV69,BSX12,2N3724A..
2N3427	Ge-PNP	AF,Sw,45V,0,5A,0,2W,B>100	2a	Mot,Sem,Stc	ASY76..77,2N1189..90
2N3428	Ge-PNP	=2N3427:B>150	2a	Mot,Sem,Stc	ASY76..77,2N1189..90
2N3429	Si-NPN	Sw,Pow,50V,5A,150W	49b	Sem,Whs	2N5387..89
2N343(A,B)	Si-NPN	AF-Driver,60V,>6MHz,A:60mA,B:65V	2a*	USA	BC174,BC190,BC546,2SC3245(A)..
2N3430	Si-NPN	=2N3429:100V	49b	Sem,Whs	2N5387..89
2N3431	Si-NPN	=2N3429:150V	49b	Sem,Whs	2N5387..89
2N3432	Si-NPN	=2N3429:200V	49b	Sem,Whs	2N5387..89
2N3433	Si-NPN	=2N3429:250V	49b	Sem,Whs	2N5388..89
2N3434	Si-NPN	=2N3429:300V	49b	Sem,Whs	2N5389
2N3435	Si-NPN	GenP,80V,0,25A,1W,>140MHz	2a$	Cen,Sty	BC140..141,BC300..301,2N2218..19A,..
2N3436	N-FET	GenP,LN,50V,Idss>3mA,Up<10	2b&	USA,Mot	2N3368,2N4341,2SK113
2N3437	N-FET	GenP,LN,50V,Idss>0,8mA,Up<5	2b&	USA,Mot	2N4340,2N5359
2N3438	N-FET	GenP,LN,50V,Idss>0,2mA,Up<2,5	2b&	USA,Mot	2N4338
2N3439(L,S)	Si-NPN	Sw,Vid,450/350V,1A,10W,15MHz	2a$	USA,EUR	BUX55,BUY59..60,2N5095
2N344	Ge-PNP	HF,5V,5mA,0,02W,50MHz	37d	Csr,Spr	AF124..127,AF200
2N3440	Si-NPN	300V,1A,10W,15MHz	-		-
2N3440(L,S)	Si-NPN	=2N3439:300/250V	2a$	USA,EUR	BSS48..49,BUX55,BUY59..60,2N5092
2N3441	Si-NPN	AF,Sw-Pow,160V,3A,25W,>0,8MHz	22a$	USA,EUR	BD241D,BD243D,2SD386(A)
2N3441X	Si-NPN	=2N3441:-/80V	22a$	-	BD241B,BD537,BD539B,BD951..
2N3441Y	Si-NPN	=2N3441:-/100V	22a$	-	BD241C,BD539C,BD953,2SD712..
2N3442	Si-NPN	AF,Sw-Pow,160V,10A,117W,>0,8MHz	23a$	USA,EUR	BD245D,BDX11,2N3773,2SD1047..
2N3443	Ge-PNP	HF,20V,0,1A,0,3W,>75MHz	2a	Cen	2N3323..25
2N3444(S)	Si-NPN	Sw,80V,1A,1W,>175MHz,<50/70ns	2a$	USA,Mic,Mot	BSV95,2N3735,2SC1069
2N3445	Si-NPN	AF,Sw-Pow,80V,7,5A,115W,16MHz,B>20	23a$	USA,Mot	BD245B,BDV93,BDW51C,BDX93,2N5874..
2N3446	Si-NPN	=2N3445:100V	23a$	USA,Mot	BD245C,BDV95,BDW51C,BDX95,2N5632..33..
2N3447	Si-NPN	=2N3445:B>40	23a$	USA,Mot	BD245B,BDV93,BDW51C,BDX93,2N5874..
2N3448	Si-NPN	=2N3445:100V,B>40	23a$	USA,Tix	BD245C,BDV95,BDW51C,BDX95,2N5632..33..
2N3449	Ge-PNP	Sw,15V,0,1A,0,15W,>300MHz	2a$	Idi,Ssi,Sty	2N705A,2N964(A),2N2635,2N2955..57
2N345	Ge-PNP	HF,5V,5mA,0,02W,50MHz	37d	Csr,Spr	AF124..127,AF200
2N3450	Si-NPN	Sw,120V,0,8A,0,6W,<100/235nS	2a$	Ray,Sty	2N2102,2N2405,2N3019..20,2SC2108
2N3451	Si-PNP	Sw,6V,0,3W,>300MHz,<35/32nS	2a$	Idi,Mic,Nsc	BSX36
2N3452	N-FET	GenP,50V,Idss>0,8mA,Up<9,8	5h+	USA,Tix	2N3365,2N4340
2N3453	N-FET	GenP,50V,Idss>0,2mA,Up<4,8	5h+	USA,Tix	2N4338,2SK40,2SK46,2SK59
2N3454	N-FET	GenP,50V,Idss>0,05mA,Up<2,3	5h+	USA,Tix	2N3367,2N3370,2N4118,J201
2N3455	N-FET	GenP,50V,Idss>0,8mA,Up<9,8	5h+	USA,Tix	2N3365,2N4340
2N3456	N-FET	GenP,50V,Idss>0,2mA,Up<4,8	5h+	USA,Tix	2N4338,2SK40,2SK46,2SK59
2N3457	N-FET	GenP,50V,Idss>0,05mA,Up<2,3	5h+	USA,Tix	2N3367,2N3370,2N4118,2N4338
2N3458	N-FET	GenP,LN,50V,Idss>3mA,Up<8	2b&	USA,Mot,Tix	BF244A,BF245A,2N3819,2N3823,2N4341...
2N3459	N-FET	GenP,LN,50V,Idss>0,8mA,Up<4	2b&	USA,Mot,Tix	2N5359
2N346	Ge-PNP	HF,5V,5mA,0,02W,75MHz	37d	Csr,Spr	AF124..125,AF200
2N3460	N-FET	GenP,LN,50V,Idss>0,2mA,Up<2	2b&	USA,Mot,Tix	2N3367,2N3370,2N4118
2N3461	Ge-PNP	AF-Driver,60V,3A,5W(Tc=25°)	2a$	Cen,Gpd	2N1039..41,2N2565..67
2N3462	Si-NPN	GenP,50V,0,03A,0,3W,>10MHz	2a$	Amp	BC167,BC182,BC237,BC547..
2N3463	Si-NPN	GenP,60V,0,03A,0,3W,>45MHz	2a$	Amp	BC174,BC182,BC190,BC546..
2N3464	Si-NPN	AF,Sw,60V,5A,5W(Tc=25°),>30MHz	2a$	Csr,Ssi,Trw	BFT32..34,BSS45,2N5336..39
2N3465	N-FET	GenP,40V,Idss>1mA,Up<10	2f&	Tdy	-
2N3466	N-FET	GenP,40V,Idss>1mA,Up<10	2f&	Tdy	-
2N3467(S)	Si-PNP	Sw,40V,1A,1W,>175MHz,B>40	2a$	USA,Mot,Tix	2SA717,2SA799
2N3468(S)	Si-PNP	=2N3467:50V,>150MHz,B>25	2a$	USA,Mot,Tix	2SA717,2SA799
2N3469	Si-NPN	AF,Sw,35V,5A,1,2W,>20MHz	2a$	USA,Tix	BFT32..34,BSS45,2N5336..39
2N347(A)	Si-NPN	AF,Sw,60V,0,06A,0,75W,3MHz	49a$	Bog	(BD517,BD519,BD525,BD527,..)
2N3470	Si-NPN	Sw,Pow,50V,10A,150W,B>100	49a$	USA,Whs	-
2N3471	Si-NPN	=2N3470:100V	49a$	USA,Whs	-
2N3472	Si-NPN	=2N3470:150V	49a$	USA,Whs	-
2N3473	Si-NPN	=2N3470:200V	49a$	USA,Whs	-
2N3474	Si-NPN	Sw,Pow,50V,10A,150W,B>350	49a$	USA,Whs	-
2N3475	Si-NPN	=2N3474:100V	49a$	USA,Whs	-
2N3476	Si-NPN	=2N3474:150V	49a$	USA,Whs	-
2N3477	Si-NPN	=2N3474:200V	49a$	USA,Whs	-
2N3478	Si-NPN	VHF/UHF,LN,30V,0,2W,900MHz	5g	USA,Mic,Rca	BF377..378,BF689,BF763,2N2857..

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2N3479..3481	UJT-P	Ip<20µA, Iv>4mA	5r$	STE	-
2N3480(A)	Si-NPN	AF, Sw, 90V, 0,05A, 0,75W, 3MHz	49a$	Bog	(BD139, BD389, BD529, BD829,..)
2N3482	UJT-P	=2N3479: Ip<2?A	5r$	-	2N4852, 2N4892
2N3483	UJT-P	=2N3479: Ip<5?A	5r$	-	2N2646, 2N4871
2N3484	UJT-P	=2N3479: Ip<5?A	5r$	-	2N2646, 2N4871
2N3485(A)	Si-PNP	=2N2906(A): 0,4W	2r$	USA, Mot, Tix	→2N2906(A)
2N3486(A)	Si-PNP	=2N2907(A): 0,4W	2r$	USA, Mot, Tix	→2N2907(A)
2N3487	Si-NPN	Sw, Pow, 80V, 7,5A, 117W, B>20	49a$	USA, Mot, Tix	2N5288..89
2N3488	Si-NPN	=2N3488: 100V	49a$	USA, Mot, Tix	2N5288..89
2N3489	Si-NPN	=2N3488: 120V, B>15	49a$	USA, Mot, Tix	2N5288..89
2N3490(A)	Si-NPN	AF, Sw, 125V, 0,04A, 0,75W, 3MHz	49a$	Bog	(BD424, BF457, BF857, 2SC2384,..)
2N3490	Si-NPN	Sw, Pow, 80V, 7,5A, 117W, B>40	49a$	USA, Mot, Tix	2N5288..89
2N3491	Si-NPN	=2N3490: 100V	49a$	USA, Mot, Tix	2N5288..89
2N3492	Si-NPN	=2N3490: 120V, B>30	49a$	USA, Mot, Tix	2N5288..89
2N3493	Si-NPN	VHF, 12V, 0,025A, 0,15W, >400MHz	5g	Etc, Sca, Ssi	BF377..378, BF689, BF763, 2N2857..
2N3494(S)	Si-PNP	GenP, 80V, 0,1A, 0,6W, >200MHz	2a$	USA, Mot, Tix	BC303, BSV17, 2SA606
2N3495(S)	Si-PNP	GenP, 120V, 0.1A, 0.6W>150MHz	2a$	USA, Mot, Tix	2N3634..37, 2SA712
2N3496	Si-PNP	=2N3494: 0,4W	2a$	USA, Mot, Tix	BC556, 2SA970, 2SA1049, 2SA1285(A)..
2N3497	SI-PNP	=2N3495: 0,4W	2a$	USA, Mot, Tix	BF398, 2SA970, 2SA1049, 2SA1285(A)..
2N3498(S)	Si-NPN	GenP, 100V, 0,5A, 1W, >150MHz, B>40	2a$	USA, Mic, Mot	BC141, BC300, BSW39, 2N1990..
2N3499(S)	Si-NPN	=2N3498: B>100	2a$	USA, Mic, Mot	BC141, BC300, BSW39, 2N1990..
2N35	Ge-NPN	AF, Sw, 25V, 8mA, 0,05W, 0,6MHz	?1a	USA	(AC127, ASY28..29)
2N35/5	Ge-NPN	AF, Sw, 40V, 0,1A, 0,15W, 0,8MHz	2a	Syl	(AC127, ASY28)
2N350	Ge-PNP	AF, Sw-Pow, 40V, 3A, 10W(Tc=75°)	23a$	USA, Mot	AD149, AUY19..20, 2N2143..46..
2N3500(S)	Si-NPN	=2N3498: 150V, 0,3A	2a$	USA, Mic, Mot	BSS43, BSW68, 2SC1860
2N3501(S)	Si-NPN	=2N3498: 150V, 0,3A, B>100	2a$	USA, Mic, Mot	BSS43, BSW68, 2SC1860
2N3502	Si-PNP	GenP, LN, 45V, 0,6A, 0,7W, <60/120nS	2a$	USA, Sgs, Tix	BC161, BC303..304, 2N3468, 2SA717..
2N3503	Si-PNP	=2N3502: 60V	2a$	USA, Sgs, Tix	BC161, BC303..304, 2SA717, 2SA742..
2N3504	Si-PNP	=2N3502: 0,4W	2a$	USA, Sgs, Tix	BC416, BC560, BSW24, 2N2906..07(A),..
2N3505	Si-PNP	=2N3502: 60V, 0,4W	2a$	USA, Sgs, Tix	BC416, BC560, BSW24, 2N2906..07(A),..
2N3506(S)	Si-NPN	Sw, 60V, 3A, 1W, <45/90nS	2a$	USA, Mot, Tix	-
2N3507(S)	Si-NPN	=2N3506: 80V	2a$	USA, Mot, Tix	-
2N3508	Si-NPN	Fast-Sw, 40V, 0,5A, 0,4W, <12/18nS, B>40	2a$	Mot, Sca, Ssi	BSS10, BSX26, BSX39, 2N3261
2N3509	Si-NPN	=2N3508: B>100	2a$	Mot, Sca, Ssi	BSS10, BSX26, BSX39, 2N3261
2N350A	Ge-PNP	=2N350: 50V, 5A, 90W	23a$	-	AL102..103, AUY21..22, 2N1545..48..
2N351	Ge-PNP	AF, Sw-Pow, 40V, 3A, 10W(Tc=75°)	23a$	USA, Mot	AD149, AUY19..20, 2N2143..46..
2N3510	Si-NPN	Fast-Sw, 40V, 0,5A, 0,36W, <20/25nS	2a$	Fch, Mot, ++	BSS10, BSX26, BSX39, 2N3261
2N3511	Si-NPN	Fast-Sw, 40V, 0,5A, 0,36W, <16/18nS	2a$	Fch, Mot, ++	BSS10, BSX26, BSX39, 2N3261
2N3512	Si-NPN	Sw, 60V, 1A, 0,8W, <30/45nS	2a$	Fer, Rca, ++	BSS27, BSV77, BSV95, 2N5189..
2N3513	Si-NPN	Dual, 80V, 0,5A, 0,3W, >50MHz	81bs	Gen	(BFX70..72, 2N2060, 2N2223)
2N3514	Si-NPN	=2N3513: 0,35W	-	Gen	-
2N3515	Si-NPN	=2N3513: 0,35W	10-FLP/ch	Gen, Mot	-
2N3516	Si-NPN	Dual, 100V, 0,5A, 0,3W, >50MHz	81bs	Gen	(BFX70..72, 2N2060, 2N2223)
2N3517	Si-NPN	=2N3514: 0,35W	-	Gen	-
2N3518	Si-NPN	=2N3514: 0,35W	10-FLP/ch	Gen, Mot	-
2N3519	Si-NPN	Dual, 60V, 0,05A, 0,35W, >30MHz	-	Gen	-
2N351A	Ge-PNP	=2N351: 50V, 5A, 90W	23a$	-	AL102..103, AUY21..22, 2N1545..48..
2N352	Ge-PNP	AF, Sw-Pow, -/40V, 2A, 25W	?23	Phc, Lte	AD149, AUY19..20, 2N2143..46..
2N3520	Si-NPN	=2N3519:	10-FLP/ch	Gen	-
2N3521	Si-NPN	Dual, 70V, 0,05A, 0,6W, >30MHz	81bs	Gen	BFX70..72, 2N2060, 2N2223
2N3522	Si-NPN	=2N3521: 0,3W	81bs	Gen	(BFX70..72, 2N2060, 2N2223)
2N3523	Si-NPN	=2N3521: 0,35W	-	Gen	-
2N3524	Si-NPN	=2N3521: 0,35W	10-FLP/ch	Gen	-
2N3525	Thy-50Hz	=2N3228: 400V	22a$	Rca, Sgs, Tag	2N4101, BStC0526L, TAG671-400, TAG676-400
2N3526	Si-NPN	Nix, 130V, 0,8W, >40MHz	2a$	Fch, Idi, Sca	BF257..259, BF657..659, 2N5058..59..
2N3527	Si-PNP	AF, 30V, 0,1A, 0,4W, >5MHz	2a$	Sca, Tdy	BC213, BC258, BC308, BC558..
2N353	Ge-PNP	AF, Sw-Pow, -/40V, 2A, 30W	?23	Phc, Lte	AD149, AUY19..20, 2N2143..46..
2N354	Si-PNP	HF/Sw, 25V, 0,05A, 0,15W, 15MHz	37d	Phc	BC213, BC258, BC308, BC558..
2N3543	Si-NPN	HF/Sw-Pow, 65V, 5A, Pq=20W(50MHz)	23a$	Itt, Trw, ++	-
2N3544	Si-NPN	VHF/UHF-Osc, 25V, 0,1A, Pq=16mW(1GHz)	2a$	USA, Mot	BFX59
2N3545	Si-PNP	GenP, 20V, 0,2A, 0,36W, <60/90nS	2a$	USA, Mic, Nsc	BC308, BC558, BSW24, 2N2906..07(A),..
2N3546	Si-PNP	Sw, 15V, 0,2A, 0,36W, <25/35nS	2a$	USA, Mic, Mot	BSX36
2N3547	Si-PNP	GenP, 60V, 0,1A, 0,4W, >45MHz	2a$	Mic, Nsc, ++	BC212, BC256, BC266, BC556..
2N3548	Si-PNP	GenP, 60V, 0,1A, 0,4W, >60MHz	2a$	Mic, Nsc, ++	BC212, BC256, BC266, BC556..

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2N3549	Si-PNP	GenP,60V,0,1A,0,4W,>60MHz	2a$	Mic,Nsc,++	BC212,BC256,BC266,BC556..
2N355	Si-PNP	HF/Sw,10V,0,05A,0,15W,15MHz	37d	Phc	BC213,BC258,BC308,BC558..
2N3550	Si-PNP	GenP,60V,0,1A,0,4W,>60MHz	2a$	Mic,Nsc,++	BC212,BC256,BC266,BC556..
2N3551	Si-NPN	Sw,Pow,115V,12A,40W,>40MHz	-	USA,Tix	-
2N3552	Si-NPN	=2N3551:140V	-	USA,Tix	-
2N3553	Si-NPN	VHF-Osc/Dr,65V,1A,Pq=2,5W(175MHz)	2a$	USA,EUR	BFW47,BFS23,BLY34,2SC2419
2N3554	Si-NPN	Sw,60V,1,2A,0,8W,<50/105nS	2a$	Sca,Sem,Tix	BSS14,2N3734..35,2N5262
2N3555	Thy-50Hz	30V,1A(Tc=100°),Igt/Ih<0,02/<3mA	2a$	Tag,Tix	2N2323A
2N3556	Thy-50Hz	=2N3555:60V	2a$	-	2N2324A
2N3557	Thy-50Hz	=2N3555:100V	2a$	-	2N2324A
2N3558	Thy-50Hz	=2N3555:200V	2a$	-	2N2326A
2N3559	Thy-50Hz	=2N3555:Igt/Ih<0,2/<5mA	2a$	-	2N2323,2N6333,TAG615-100,(MCR606-2)
2N356(A)	Ge-NPN	Sw,20(A:30)V,0,5A(ss),0,1(A:0,15)W	2a	USA	ASY28..29,ASY73..75
2N3560	Thy-50Hz	=2N3556:Igt/Ih<0,2/<5mA	2a$	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N3561	Thy-50Hz	=2N3557:Igt/Ih<0,2/<5mA	2a$	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N3562	Thy-50Hz	=2N3558:Igt/Ih<0,2/<5mA	2a$	-	2N2326,2N6335,TAG615-200,(MCR606-4)
2N3563	Si-NPN	UHF/IF,30V,0,05A,0,2W,>600MHz	8a	USA,Mic,Sgs	BF377..378,BF689,BF763,2N2857..
2N3564	Si-NPN	VHF/IF,30V,0,05A,0,2W,>600MHz	8a	USA,Mic,Sgs	BF370,BF920..921(S),BF959
2N3565	Si-NPN	GenP,30V,0,05A,0,2W,>40MHz	8a	USA,Mic,Sgs	BC168,BC183,BC238,BC548..
2N3566	Si-NPN	GenP,40V,0,2A,0,3W,>40MHz	8a	USA,Mic,Sgs	BC167,BC182,BC237,BC547..
2N3567	Si-NPN	GenP,80/40V,0,5A,0,3W,>60MHz,B>40	8a	USA,Mic,Sgs	BC639,BCX24,2N3700..01,2SD667..
2N3568	Si-NPN	=2N3567:80/60V	8a	USA,Mic,Sgs	BC639,BCX24,2N3700..01,2SD667..
2N3569	Si-NPN	=2N3567:B>100	8a	USA,Mic,Sgs	BC639,BCX24,2N3700..01,2SD667..
2N357(A)	Ge-NPN	Sw,20(A:30)V,0,5A(ss),0,1(A:0,15)W	2a	USA	ASY28..29,ASY73..75
2N3570	Si-NPN	VHF/UHF,LN,30V,0,05A,1700MHz	5g	USA,EUR	BFR37,BFW30,BFX59,BFX73
2N3571	Si-NPN	VHF/UHF,LN,30V,0,05A,0,2W 1.4GHz	5g	USA,EUR	BFR37,BFW30,BFX59,BFX73
2N3572	Si-NPN	VHF/UHF,LN,30V,0,05A,1200MHz	5g	USA,EUR	BFR37,BFW30,BFX59,BFX73
2N3573	P-FET	GenP,25V,Idss>0,02mA,Up<2V	5g+	TI	2N5471
2N3574	P-FET	GenP,25V,Idss>0,075mA,Up<2V	5g+	TI	2N2841..42,2N5472
2N3575	P-FET	GenP,25V,Idss>0,2mA,Up<4V	5g+	TI	2N2843
2N3576	Si-PNP	Sw,20V,0,2A,0,36W,<30/50nS	2a$	USA,Mic,Tix	BSX36
2N3577	Si-NPN	Sw,Pow,100V,2A,85W,>10MHz	-	TI	2N1722..23,(2SC2681,2SC2706,2SC2837)
2N3578	P-FET	GenP,20V,Idss>0,9mA,Up<4V	2a&	Isi,Six,Tix	2N2608,2N5266
2N3579	Si-PNP	GenP,60V,0,03A,0,4W,>80MHz,B>30	2a$	Sca,Sem,Ssi	BC212,BC256,BC266,BC556..
2N358(A)	Ge-NPN	Sw,20(A:30)V,0,5A(ss),0,1(A:0,15)W	2a	USA	ASY28..29,ASY73..75
2N3580	Si-PNP	=2N3579:B>60	2a$	Sca,Sem,Ssi	BC212,BC256,BC266,BC556..
2N3581	Si-PNP	GenP,50V,0,03A,0,4W,>30MHz,B>50	2a$	Sca,Sem,Ssi	BC212,BC257,BC307,BC557..
2N3582	Si-PNP	=2N3581:B>100	2a$	Sca,Sem,Ssi	BC212,BC257,BC307,BC557..
2N3583	Si-NPN	Sw,Pow,250/175V,2A,35W,>10MHz	22a$	Mot,Tho,++	BUX84,TIP75(A..C),2N4240,2SC3169,..
2N3584	Si-NPN	=2N3583:375/250V	22a$	Mot,Tho,++	BUX84,TIP75A..C,2N4240,2SC3169..
2N3585	Si-NPN	=2N3583:500/300V	22a$	Mot,Tho,++	BUX84,TIP75C,2N4240,2SC3169..
2N3586	Si-PNP	Dual,Chopper,45V,0,1A,0,25W	-	Nsc	-
2N3587	Si-NPN	Dual,60V,0,5A,>80MHz	81bs	Mic,Nsc,Sgs	BFX70..72,2N2060,2N2223
2N3588	Ge-PNP	VHF,25V,10mA,0,1W,>200MHz	5g	Phi,Ssi	AF106,AF109R,AF306,2N3323..25
2N3589	Si-NPN	Sw,Pow,200V,0,5A,>15MHz,B>30	43a$	USA	(BF466..468,BF757..759,MJE340,..)
2N359	Ge-PNP	AF,Sw,25V,0,4A,0,17W,>3,5MHz	2a	USA	AC128,AC152..153,AC188
2N3590	Si-NPN	=2N3589:B>75	43a$	USA	(BF466..468,BF757..759,MJE340,..)
2N3591	Si-NPN	=2N3589:	5g	USA	(BF466..468,BF757..759,MJE340,..)
2N3592	Si-NPN	=2N3589:B>75	5g	USA	(BF466..468,BF757..759,MJE340,..)
2N3593	Si-NPN	=2N3589:	49a$	USA	(BF466..468,BF757..759,MJE340,..)
2N3594	Si-NPN	=2N3589:B>75	49a$	USA	(BF466..468,BF757..759,MJE340,..)
2N3595	Si-NPN	=2N3589:	49a$	USA	(BF466..468,BF757..759,MJE340,..)
2N3596	Si-NPN	=2N3589:B>75	49a$	USA	(BF466..468,BF757..759,MJE340,..)
2N3597	Si-NPN	Sw,Pow,60/40V,20A,100W(Tc=100°)	49a$	USA,Tix	2N2815..22,2N5539
2N3598	Si-NPN	=2N3597:80/60V	49a$	USA,Tix	2N2815..22,2N5539
2N3599	Si-NPN	=2N3597:100/80V	49a$	USA,Tix	2N2816..18,2N2820..22,2N5539
2N36	Ge-PNP	AF/HF,20V,8mA,0,05W,0,8MHz	?1a	USA	(AC125..126,AC151,ASY26..27)
2N360	Ge-PNP	AF,Sw,32V,0,4A,0,17W,>2,5MHz	2a	USA	AC128,AC152..153
2N3600	Si-NPN	VHF,LN,30V,0,05A,0,2W,>850MHz	5g	USA,EUR	BF377..378,BF689,BF763,2N2857..
2N3601	Ge-PNP	AF,Sw,100V,3,5A,0,5W,>20MHz	2a	Sty,Tix	-
2N3602	Ge-PNP	AF,Sw,100V,3,5A,0,75W,>20MHz	49a	Sty,Tix	-
2N3603	Ge-PNP	AF,Sw,130V,3,5A,0,5W,>20MHz	2a	Sty,Tix	-
2N3604	Ge-PNP	AF,Sw,130V,3,5A,0,75W,>20MHz	49a	Sty,Tix	-
2N3605	Si-NPN	Sw,18V,0,2A,0,2W,>300MHz,<35/45nS	7c	Nsc,Tho,++	BSS10..11,BSX19..20,2N2368..69(A),..

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2N3605A	Si-NPN	=2N3605: 40V	7c	-	BSS10..11, BSX19..20, 2N2368..69(A),..
2N3606	Si-NPN	=2N3605: <40/60nS	7c	Nsc,Tho,++	BSS10..11, BSX19..20, 2N2368..69(A),..
2N3606A	Si-NPN	=2N3605: 40V, <40/60nS	7c	-	BSS10..11, BSX19..20, 2N2368..69(A),..
2N3607	Si-NPN	=2N3605: <45/70nS	7c	Nsc,Tho,++	BSS10..11, BSX19..20, 2N2368..69(A),..
2N3608	MOS-P-FET-e	Sw,25V, Idss<7mA, Up<6V	5l+	Dio,Gie	-
2N3609	MOS-P-FET-e	Dual,25V, Idss<3,2mA, Up<6V	81ca+	Dio,Gie	-
2N361	Ge-PNP	AF,Sw,32V,0,4A,0,17W,>2,5MHz	2a	USA	AC128, AC152..153
2N3610	MOS-P-FET-e	Sw,20V, Idss<0,6mA, Up<7V	5l+	Dio,Gie	-
2N3611	Ge-PNP	AF,Sw-Pow,40V,7A,77W,B>35	23a$	USA,Mot	AL102..103, AUY22, 2N2288..93..
2N3612	Ge-PNP	=2N3611: 60V	23a$	USA,Mot	AL102..103, AUY22, 2N2292..93..
2N3613	Ge-PNP	=2N3611: B>60	23a$	USA,Mot	AL102..103, AUY22, 2N2288..93..
2N3614	Ge-PNP	=2N3611: 60V, B>60	23a$	USA,Mot	AL102..103, AUY22, 2N2292..93..
2N3615	Ge-PNP	AF,Sw-Pow,80V,7A,77W,B>30	23a$	USA,Mot	AL102..103, AUY22, 2N2292..93..
2N3616	Ge-PNP	=2N3615: 100V	23a$	USA,Mot	AL102..103, 2N2290, 2N2293
2N3617	Ge-PNP	=2N3615: B>45	23a$	USA,Mot	AL102..103, AUY22, 2N2292..93..
2N3618	Ge-PNP	=2N3615: 100V, B>45	23a$	USA,Mot	AL102..103, 2N2290, 2N2293
2N3619	Si-NPN	Sw,Pow,75V,2,5A,7,5W(Tc=25°),>200MHz	2a$	Sca,Sol,Ssi	BSS15, BSV84, BSX64, 2N5320
2N362	Ge-PNP	AF,Sw,25V,0,2A,0,17W,>2MHz	2a	USA	AC128, AC152..153, AC188
2N3620	Si-NPN	Sw,Pow,75V,5A,7,5W,>200MHz	?49a$	Sca,Sol,Ssi	-
2N3621	Si-NPN	Sw,Pow,75V,10A,30W,>200MHz	49a	Sca,Sol,Ssi	-
2N3622	Si-NPN	Sw,Pow,75V,10A,30W,>200MHz	49a$	Sca,Sol,Ssi	-
2N3623	Si-NPN	Sw,Pow,75V,2,5A,7,5W(Tc=25°),>200MHz	2a$	Sca,Sol,Ssi	BSS15, BSV84, BSX64, 2N5320
2N3624	Si-NPN	Sw,Pow,75V,5A,7,5W,>200MHz	?49a$	Sca,Sol,Ssi	-
2N3625	Si-NPN	Sw,Pow,75V,10A,30W,>200MHz	49a	Sca,Sol,Ssi	-
2N3626	Si-NPN	Sw,Pow,75V,10A,30W,>200MHz	49a$	Sca,Sol,Ssi	-
2N3627	Si-NPN	Sw,Pow,100V,2,5A,7,5W(Tc=25°),>200MHz	2a$	Sca,Sol,Ssi	BSS15, BSV84, BSX64, 2N5320
2N3628	Si-NPN	Sw,Pow,100V,5A,7,5W,>200MHz	?49a$	Sca,Sol,Ssi	-
2N3629	Si-NPN	Sw,Pow,100V,10A,30W,>200MHz	49a	Sca,Sol,Ssi	-
2N363	Ge-PNP	AF,Sw,32V,0,2A,0,17W,>1,5MHz	2a	USA	AC128, AC152..153
2N3630	Si-NPN	Sw,Pow,100V,10A,30W,>200MHz	49a$	Sca,Sol,Ssi	-
2N3631	MOS-N-FET-d	GenP,20V, Idss>2mA, Up<6V	2a*	Six	2N3797
2N3632	Si-NPN	VHF-Pow,65V,3A,Pq=13,5W(175MHz)	49a	USA,EUR	-
2N3633	Si-NPN	Fast-Sw,15V,0,05A,0,3W,<9/9nS	2a$	USA	BSV89..92, BSX27, BSX44, 2N2475..
2N3634(S)	Si-PNP	AF,Sw,140V,1A,1W,>150MHz,B>50	2a$	USA,Mot,Tix	BFT19A,B, BFT28(A..C), 2N5415
2N3635(S)	Si-PNP	=2N3634: B>100	2a$	USA,Mot,Tix	BFT19A,B, BFT28(A..C), 2N5415
2N3636(S)	Si-PNP	=2N3634: 175V	2a$	USA,Mot,Tix	BFT19A,B, BFT28A..C, 2N5415
2N3637(S)	Si-PNP	=2N3634: 175V, B>100	2a$	USA,Mot,Tix	BFT19A,B, BFT28A..C, 2N5415
2N3638(A)	Si-PNP	AF,Sw,25V,0,5A,0,3W,<90/170nS	8a	Fch,Nsc,Sgs	BC160..161, BC303..304, 2N3072..73..
2N3639	Si-PNP	Sw,6V,0,08A,0,2W,<30/32nS	8a	Fch,Nsc,Sgs	BSX36
2N364	Ge-NPN	AF,Sw,30V,0,05A,0,15W,2,5MHz	?1a	Csr,Etc	AC127, ASY28, ASY73..75
2N3640	Si-PNP	=2N3639: 12V	8a	Fch,Nsc,Sgs	BSX36
2N3641	Si-NPN	AF,Sw,60/30V,0,5A,0,35W,>250MHz,B>40	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,..
2N3642	Si-NPN	=2N3641: 60/45V	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,..
2N3643	Si-NPN	=2N3641: B>100	8a	Fch,Nsc,Sgs	BC337A, BC637, BC639, 2N3299..3300,..
2N3644	Si-PNP	AF,Sw,45V,0,5A,0,3W,>200MHz	8a	Fch,Nsc,Sgs	BC327, BC638, BC640, 2N3072..73..
2N3645	Si-PNP	=2N3644: 60V	8a	Fch,Nsc,Sgs	BC327A, BC638, BC640, 2N3072..73..
2N3646	Si-NPN	Sw,40V,0,2A,0,2W,<25/35nS	8a	Fch,Nsc,Sgs	BSS10..11, BSX19..20, 2N2368..69(A),..
2N3647	Si-NPN	=2N3510: 0,4W	2a$	USA,Mot,Sgs	→2N3510
2N3648	Si-NPN	=2N3511: 0,4W	2a$	USA,Mot,Sgs	→2N3511
2N3649	Thy-Fast	50V,25A(Tc=40°) Igt/Ih<180/<150mA,<15µS	21b$	USA,Tag,Tho	BTW28/500R, CS15,9-04
2N365	Ge-NPN	AF,Sw,30V,0,05A,0,15W,3MHz	?1a	Csr,Etc	AC127, ASY28, ASY73..75
2N3650	Thy-Fast	=2N3649: 100V	21b$	-	BTW28/500R, CS15,9-04
2N3651	Thy-Fast	=2N3649: 200V	21b$	-	BTW28/500R, CS15,9-04
2N3652	Thy-Fast	=2N3649: 300V	21b$	-	BTW28/500R, CS15,9-04
2N3653	Thy-Fast	=2N3649: 400V	21b$	-	BTW28/500R, CS15,9-04
2N3654	Thy-Fast	=2N3649: <10µS	21b$	-	BTW28/500R, CS15,9-04
2N3655	Thy-Fast	=2N3650: <10µS	21b$	-	BTW28/500R, CS15,9-04
2N3656	Thy-Fast	=2N3651: <10µS	21b$	-	BTW28/500R, CS15,9-04
2N3657	Thy-Fast	=2N3652: <10µS	21b$	-	BTW28/500R, CS15,9-04
2N3658	Thy-Fast	=2N3653: <10µS	21b$	-	BTW28/500R, CS15,9-04
2N3659	Si-NPN	Sw,Vid,220V,0,5A,4W(Tc=25°),>50MHz	2a$	USA	BSS48..40, 2N3440, 2SD576
2N366	Ge-NPN	AF,Sw,30V,0,05A,0,15W,3,5MHz	?1a	Csr,Etc	AC127, ASY28, ASY73..75
2N3660	Si-PNP	GenP,40V,1,5A,5W(Tc=25°),>25MHz	2a$	USA	BC461, BCX60, BSV17, 2N5322..23..
2N3661	Si-PNP	=2N3660: 60V	2a$	USA	BC461, BCX60, BSV17, 2N5322..23..

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2N3662	Si-NPN	VHF/IF,18V,0,025A,0,2W,1000MHz	7c	Gen,Nsc,Sem	BF225,BF314,BF502,BF505,BF507..
2N3663	Si-NPN	VHF/IF,30V,0,025A,0,2W,1000MHz	7c	Gen,Nsc,Sem	BF225,BF314,BF502,BF505,BF507..
2N3664	Si-NPN	HF/UHF-Out,60V,0,5A,Pq>2,2W(250MHz)	49a$	Mot,Sca	-
2N3665	Si-NPN	AF,Sw,120V,1A,0,3W,>60MHz,B>40	2a$	USA,Nsc,Tix	BSS42..43,2N2102,2N2405,2N3019..20..
2N3666	Si-NPN	=2N3665:B>100	2a$	USA,Nsc,Tix	BSS42..43,2N2102,2N2405,2N3019..20..
2N3667	Si-NPN	Sw,Pow,50V,15A,117W,>0,5MHz	23a$	USA	BD315,BD745,BDW51C,BDX13,2N3055..
2N3668	Thy-50Hz	100V,8A(Tc=80°),Igt/Ih<40/<50mA	23a$	RCA	2N2575
2N3669	Thy-50Hz	=2N3668:200V	23a$	-	2N2576
2N367	Ge-PNP	AF,Sw,30V,0,05A,0,1W,0,7MHz	?1a	Csr,Etc	AC125..126,AC151,ASY26
2N3670	Thy-50Hz	=2N3668:400V	23a$	-	2N2578
2N3671	Si-PNP	Sw,60V,0,6A,0,6W,35/80nS	2a$	USA,Fch	2SA717,2SA742
2N3672	Si-PNP	=2N3671:0,4W	2a$	USA,Fch	BSW24,2N2906..07(A)
2N3673	Si-PNP	=2N3671:0,35W	2a$	USA,Fch,Mot	BSW24,2N2906..07(A)
2N3675	Si-NPN	Sw,90/55V,3A,8,8W(Tc=25°),>1MHz	2a$	USA,Tix	BSX64,BUY41,2N4239,2SC2214..
2N3676	Si-NPN	=2N3675:90/90V	2a$	USA,Tix	BSX64,BUY41,2N4239,2SC2214..
2N3677	Si-PNP	Chopper,30/20/30V,0,1A,0,4W,>5MHz	2a$	USA,Mot	2N2946
2N3678	Si-NPN	GenP,75V,0,8A,0,8W,<40/250nS	2a$	Fch,Nsc,++	BSW39,BSW53..54,2N2218..19A,2N3444
2N3679	UJT-P	Iv>4,2mA	S	Gen	-
2N368	Ge-PNP	AF,Sw,30V,0,05A,0,1W,1MHz	?1a	Csr,Etc	AC125..126,AC151,ASY26
2N3680	Si-NPN	Dual,LN,60V,0,03A,0,6W,>60MHz	81bs	USA,Sgs,Tix	BFX70..72,2N2060,2N2223
2N3681	Si-NPN	UHF,10V,0,025A,0,2W,>1000MHz	5g	Etc,Sca,Ssi	BF377..378,BF689,BF763,2N2857..
2N3682	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<12/-nS	2a$	TI	BSS10..11,BSX19..20,2N2368..69(A),..
2N3683	Si-NPN	UHF,30V,0,03A,0,2W,>1000MHz	5g	USA,Fch	BF377..378,BF689,BF763,2N2857..
2N3684(A)	N-FET	GenP,LN,50V,Idss>2,5mA,Up<5V	5h+	Isi,Nsc,++	BF256A,BFS71,2N3822,2N4221..
2N3685(A)	N-FET	GenP,LN,50V,Idss>1mA,Up<3,5V	5h+	Isi,Nsc,++	BFW12,2N4340,2N5484
2N3686(A)	N-FET	GenP,LN,50V,Idss>0,4mA,Up<2V	5h+	Isi,Nsc,++	2N4339,2N5358,2SK83,2SK193,2SK195,..
2N3687(A)	N-FET	GenP,LN,50V,Idss>0,1mA,Up<1,2V	5h+	Isi,Nsc,++	2N4117,2SK92..93,2SK103
2N3688	Si-NPN	VHF/IF,AGC,40V,0,03A,0,2W,>400MHz	8a	Fch,Sgs	BF198,BF225,BF310,BF367,BF596..
2N3689	Si-NPN	VHF/IF,AGC,40V,0,03A,0,2W,>400MHz	8a	Fch,Sgs	BF198,BF225,BF310,BF367,BF596..
2N369	Ge-PNP	AF,Sw,30V,0,05A,0,1W,1,3MHz	?1a	Csr,Etc	AC125..126,AC151,ASY26
2N3690	Si-NPN	VHF/IF,AGC,40V,0,03A,0,2W,>400MHz	8a	Fch,Sgs	BF198,BF225,BF310,BF367,BF596..
2N3691	Si-NPN	HF,35V,0,05A,0,2W,260MHz	8a	USA,Mic,Sgs	BF240..241,BF254..255,BF594..595,..
2N3692	Si-NPN	HF,35V,0,05A,0,2W,260MHz	8a	USA,Mic,Sgs	BF240..241,BF254..255,BF594..595,..
2N3693	Si-NPN	FM-IF,45V,0,05A,0,2W,400MHz	8a	USA,Mic,Sgs	BF240..241,BF254..255,BF594..595,..
2N3694	Si-NPN	FM-IF,45V,0,05A,0,2W,400MHz	8a	USA,Mic,Sgs	BF240..241,BF254..255,BF594..595,..
2N3695	P-FET	GenP,LN,30V,Idss>1,75mA,Up<4,5V	5g+	Tsc	2N2609
2N3696	P-FET	GenP,LN,30V,Idss>0,5mA,Up<3,2V	5g+	Tsc	-
2N3697	P-FET	GenP,LN,30V,Idss>0,2mA,Up<1,8V	5g+	Tsc	2N2843
2N3698	P-FET	GenP,LN,30V,Idss>0,05mA,Up<1,1V	5g+	Tsc	-
2N37	Ge-PNP	AF/HF,20V,8mA,0,05W,0,6MHz	?1a	USA	(AC125..126,AC151,ASY26..27)
2N370	Ge-PNP	HF,24V,10mA,0,08W,30MHz	1g	Rca	AF124..127,AF200
2N370/33	Ge-PNP	=2N370:	5g	Syl	AF124..127,AF200
2N3700	Si-NPN	GenP,140V,1A,0,5W,200MHz,B>100	2a$	USA,EUR	BSS59,2SC2383,2SC3228
2N3701	Si-NPN	=2N3700:B>40	2a$	USA,EUR	BSS59,2SC2383,2SC3228
2N3702	Si-PNP	GenP,40V,0,2A,0,3W,>100MHz,B>60	7c	USA,Aeg,Tix	BC212,BC257,BC307,BCS57..
2N3703	Si-PNP	=2N3702:45V,B>30	7c	USA,Aeg,Tix	BC212,BC257,BC307,BCS57..
2N3704	Si-NPN	GenP,50V,0,8A,0,36W,>100MHz,B>100	7c	USA,Aeg,Tix	BC337,BC637,BC639,2SD667..
2N3705	Si-NPN	=2N3704:B>50	7c	USA,Aeg,Tix	BC337,BC637,BC639,2SD667..
2N3706	Si-NPN	=2N3704:40V,B>30	7c	USA,Aeg,Tix	BC337,BC635,BC637,BC639..
2N3707	Si-NPN	AF-Pre,LN,30V,0,03A,0,36W,80MHz	7c	USA,Aeg,Tix	BC169,BC184,BC239,BCS49..
2N3708	Si-NPN	AF,30V,0,03A,0,36W,80MHz,B=45/660	7c	USA,Aeg,Tix	BC168,BC183,BC238,BCS48..
2N3709	Si-NPN	=2N3708:B=45..165	7c	USA,Aeg,Tix	BC168,BC183,BC238,BCS48..
2N371	Ge-PNP	HF,24V,10mA,0,08W,30MHz	1g	Rca	AF124..127,AF200
2N371/33	Ge-PNP	=2N371:	5g	Syl	AF124..127,AF200
2N3710	Si-NPN	=2N3708:B=90..330	7c	USA,Aeg,Tix	BC168,BC183,BC238,BCS48..
2N3711	Si-NPN	=2N3708:B=180..600	7c	USA,Aeg,Tix	BC168,BC183,BC238,BCS48..
2N3712(S)	Si-NPN	Vid,150V,0,2A,1W,>40MHz	2a$	USA,Mot,Tix	BF257..259,BF657..759,2N5058..59..
2N3713	Si-NPN	AF,Sw-Pow,80V,10A,150W,>4MHz,B>25	23a$	USA,Mot,Sgs	BD545B,BD315,BDW51C,2N3772,2N5632..34..
2N3714	Si-NPN	=2N3713:100V	23a$	-	BD545C,BD317,2N3772,2N5632..34..
2N3715	Si-NPN	=2N3713:B>50	23a$	-	BD545B,BD315,BDW51C,2N3772,2N5632..34..
2N3716	Si-NPN	100V,10A,150W,4MHz,B>50	23a$	-	BD545C,BD317,BDW51C,2N3772,2N5632..34..
2N3717	Si-NPN	HF/Sw,60V,1A,7,5W(Tc=25°),250MHz	2a$	Mot	2N3553,2SC2419
2N3718	Si-NPN	HF/Sw,60V,1A,10W(Tc=25°),250MHz	49a	Mot	BLY60
2N3719	Si-PNP	Sw,40V,3A,1W,>60MHz,<100/400nS	2a$	USA,Mot,Tix	2N3867..68,2N6303,BSS44

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2N372	Ge-PNP	HF,24V,10mA,0,08W,30MHz	1g	Rca	AF124..127,AF200
2N372/33	Ge-PNP	=2N372:	5g	Syl	AF124..127,AF200
2N3720	Si-PNP	=2N3719:60V	2a$	USA,Mot,Tix	2N3868,2N6303,BS544
2N3721	Si-NPN	GenP,18V,0,1A,0,36W,120MHz	7c	USA,Gen,Mic	BC168,BC183,BC238,BC548..
2N3722	Si-NPN	Sw,80V,0,5A,0,8W,>300MHz,<62/130nS	2a$	USA,Mot	BSV95,2N3725,2SC1069
2N3723	Si-NPN	=2N3722:100V,<85/160nS	2a$	USA,Mot	BSW39,2SC1069
2N3724	Si-NPN	Sw,50V,0,5A,0,8W,>300MHz,20/55ns	2a$	USA,Fer,Itt	BSV77,BSV95,2N3722..23,2N5189..
2N3724A	Si-NPN	=2N3724:1,2A	2a$	-	BSS14,2N3734..35,2N5262
2N3725	Si-NPN	80V,0.5A,1W,35/60nS	2a$	=2N3724	BSV95,2N3722..23,2SC1069
2N3725A	Si-NPN	=2N3725:1,2A	2a$	-	BSS14,2N3735,2N5262
2N3726	Si-PNP	Dual,LN,45V,0,3A,0,5W,>200MHz	81bs	USA,Fch,Mic	2N4015..4016
2N3727	Si-PNP	Dual,LN,45V,0,3A,0,5W,>200MHz	81bs	=2N3727	2N4015..4016
2N3728	Si-NPN	Dual,60V,0,5A,0,45W,>80MHz	81bs	Fch,Ray,Sca	BFX70..72,2N2060,2N2223
2N3729	Si-NPN	Dual,60V,0,5A,0,45W,>80MHz	81bs	=2N3728	BFX70..72,2N2060,2N2223
2N373	Ge-PNP	HF,24V,10mA,0,08W,30MHz	1g	Rca	AF124..127,AF200
2N373/33	Ge-PNP	=2N373:	5g	Syl	AF124..127,AF200
2N3730	Ge-PNP	TV-HD,200V,3A,10W(Tc=55°)	23a$	Gpd,Rca	AU107,AU113,AU213,2N5324
2N3731	Ge-PNP	TV-HD,320V,10A(ss),5W(Tc=55°)	23a$	Gpd,Rca	AU106,AU109,AU111..112,2N5325
2N3732	Ge-PNP	TV-HD,100V,3A,3W(Tc=55°)	23a$	Gpd,Rca	AU108,AU110,AU210
2N3733	Si-NPN	VHF/UHF-Pow,65V,3A,Pq>10W(400MHz)	49a	USA,EUR	-
2N3734(S)	Si-NPN	Sw,Dr,50V,1,5A,1W,>250MHz,<48/60nS	2a$	-	BSS14,2N5262
2N3735(S)	Si-NPN	=2N3734:75V	2a$	USA,EUR	BSS14,2N5262
2N3736	Si-NPN	=2N3734:0,5W	2a$	USA,EUR	-
2N3737	Si-NPN	=2N3734:75V,0,5W	2a$	-	-
2N3738	Si-NPN	AF,Sw-Pow,250/225V,1A,20W,>10MHz	22a$	USA,Mot,Tho	BUW40(A,B),BUX84,2N4296..97..
2N3739	Si-NPN	=2N3738:325/300V	22a$	USA,Mot,Tho	BUW40(A,B),BUX84,2N4296..97..
2N374	Ge-PNP	HF,24V,10mA,0,08W,30MHz	5g	Gen	AF124..127,AF200
2N3740(A)	Si-PNP	AF,Sw-Pow,60V,4A,25W,>4MHz	22a$	USA,Fch,Mot	BD244A,BD540A,BDX14,2N6313..14..
2N3741(A)	Si-PNP	AF,Sw-Pow,80V,4A,25W,>4MHz	22a$	-	BD244B,BD540B,BDX14,2N6314..
2N3742(S)	Si-NPN	Vid,300V,0,05A,1W,>30MHz	2a$	Mot,Nsc,Sca	BF259,BF659,BFR59,BFS89,2N5058
2N3743(S)	Si-PNP	Vid,300V,0,05A,1W,>30MHz	2a$	Mot,Nsc,Sca	BFT44,BFQ37,2SB622
2N3744	Si-NPN	Sw,Pow,60V,5A,30W(Tc=100°),>30MHz	50g	USA,Tix	-
2N3745	Si-NPN	=2N3744:80V	50g	-	-
2N3746	Si-NPN	=2N3744:100V	50g	-	-
2N3747	Si-NPN	Sw,Pow,60V,5A,30W(Tc=100°),>40MHz	50g	USA,Tix	-
2N3748	Si-NPN	=2N3747:80V	50g	-	-
2N3749	Si-NPN	=2N3747:100V	50g	-	-
2N375	Ge-PNP	AF,Sw-Pow,80V,Ueb=40V,3A,106W	23a$	USA,Mot	2N1536..48,2N1541..43,2N3615..18..
2N3750	Si-NPN	Sw,Pow,60V,5A,30W(Tc=100°),>50MHz	50g	USA,Tix	-
2N3751	Si-NPN	=2N3750:80V	50g	-	-
2N3752	Si-NPN	=2N3750:100V	50g	-	-
2N376	Ge-PNP	AF,Sw-Pow,40V,3A,90W	23a$	USA,Mot	2N1529..48,2N2138..41,2N2143..46..
2N3762(S)	Si-PNP	Sw,Dr,40V,1,5A,1W,>180MHz,<43/115nS	2a$	USA,Mot	BSV82,2SA799
2N3763(S)	Si-PNP	=2N3762:60V	2a$	-	BSV82,2SA799
2N3764(A)	Si-PNP	=2N3762:0,5W	2a$	-	-
2N3765	Si-PNP	=2N3762:60V,0,5W	2a$	-	-
2N3766	Si-NPN	AF,Sw-Pow,80V,4A,20W,>10MHz	22a$	USA,Fch,Mot	BD243B,BD539B,BD951,2N3054..
2N3767	Si-NPN	100V,4A,20W,>10MHz	22a$	-	BD243C,BD539C,BD953,2N3054..
2N376A	Ge-PNP	=2N376:50V,5A	23a$	-	2N1535..38,2N1545..48,2N3615..18..
2N377	Ge-NPN	Sw,25V,Ueb=15V,0,2A,0,15W,6MHz	2a&	USA,Tix	ASY28..29,ASY73..75
2N3770	Ge-PNP	HF,10V,0,05A,0,05W,>100MHz	2a	Spr	AF106,AF109R,AF306,2N3323..25
2N3771	Si-NPN	AF,Sw-Pow,50V,30A,150W,>0,2MHz	23a$	USA,EUR,Tos	BDX41,BDY29,MJ802,2SD630..631
2N3772	Si-NPN	AF,Sw-Pow,100V,20A,150W,>0,2MHz	23a$	USA,EUR,Tos	BDX40,BDY29,MJ802,2SD797
2N3773	Si-NPN	AF,Sw-Pow,160V,16A,150W,>0,2MHz	23a$	USA,EUR,Tos	BDW32..36,BDX50,MJ15015,2SC2608
2N3774	Si-PNP	AF,Sw,40V,1A,5W(Tc=100°),>1MHz,B>20	2a$	USA,Tix	BSS17..18,BSW40,BSV82,2N5322..23
2N3775	Si-PNP	=2N3774:60V	2a$	-	BSS17..18,BSW40,BSV82,2N5322..23
2N3776	Si-PNP	=2N3774:80V	2a$	-	BSS17..18,BSW40,BSV82,2N5322..23
2N3777	Si-PNP	=2N3774:100V	2a$	-	BSS17,BSW40,2N5322
2N3778	Si-PNP	=2N3774:B>10	2a$	USA,Tix	BSS17..18,BSW40,BSV82,2N5322..23
2N3779	Si-PNP	=2N3774:60V,B>10	2a$	-	BSS17..18,BSW40,BSV82,2N5322..23
2N377A	Ge-NPN	=2N377:40V	2a&	-	-
2N378	Ge-PNP	AF,Sw-Pow,40V,5A,106W	23a$	USA,Mot	2N1529..38,2N1539..48,2N3611..18..
2N3780	Si-PNP	=2N3774:80V,B>10	2a$	-	BSS17..18,BSW40,BSV82,2N5322..23
2N3781	Si-PNP	=2N3774:100V,B>10	2a$	-	BSS17,BSW40,2N5322

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2N3782	Si-PNP	=2N3774:3A,B>10	2a$	USA,Tix	2N3719..20,2N3867..68,2N4234..36
2N3783	Ge-PNP	UHF,30V,0,02A,0,15W,>800MHz	5g	Mot,Ssi	AF139,AF239(S),2N3279..86
2N3784	Ge-PNP	UHF,30V,0,02A,0,15W,>700MHz	5g	Mot,Ssi	AF139,AF239(S),2N3279..86
2N3785	Ge-PNP	UHF,15V,0,02A,0,15W,>700MHz	5g	Mot,Ssi	AF139,AF239(S),2N3279..86
2N3788	Si-NPN	TV-HD,400/325V,2A,100W	23a$	Sol,Ssi,Stc	BU104,BU606,BU608
2N3789	Si-PNP	AF,Sw-Pow,60V,10A,150W,>4MHz,B>25	23a$	USA,Mot,Sgs	BD546A,BD316,BDW51C,2N6029..31,2N6229..31,..
2N379	Ge-PNP	=2N378:80V	23a$	USA,Mot	2N1536..38,2N1546..48,2N3615..18..
2N3790	Si-PNP	=2N3789:80V	23a$	-	BD546B,BD318,BDW52C,2N6029..31,2N6229..31,..
2N3791	Si-PNP	=2N3789:B>50	23a$	-	BD546A,BD316,,2N6029..31,2N6229..31,..
2N3792	Si-PNP	80V,10A,150W,4MHz,B>50	23a$	-	BD546B,BD318,BDW52C,2N6029..31,2N6229..31,..
2N3793	Si-NPN	AF,40V,0,3A,0,25W,220MHz,B>20	?40b	USA,Mic,Pih	BC337,BC635,BC637,BC639..
2N3794	Si-NPN	=2N3793:100MHz,B>100	?40b	-	BC337,BC635,BC637,BC639..
2N3795	Si-PNP	AF,Sw,120V,1A,5W(Tc=25°),>0,5MHz	2a$	Csr,Ssi,Stc	2N3634..37,2N5415
2N3796	MOS-N-FET-d	AF,30V,Idss>0,5mA,Up<4V	2a*+	Mot	-
2N3797	MOS-N-FET-d	AF,30V,Idss>2mA,Up<7V	2a*+	Mot	-
2N3798	Si-PNP	GenP,LN,60V,0,05A,0,36W,B>150	2a$	USA,Mot,Tix	2SA872(A),2SA941..942,2SA970..
2N3798A	Si-PNP	=2N3798:90V	2a$	-	2SA872(A),2SA941..942,2SA970..
2N3799	Si-PNP	=2N3798:B>300	2a$	-	2SA872(A),2SA941..942,2SA970..
2N3799A	Si-PNP	=2N3798:90V,B>300	2a$	-	2SA872(A),2SA941..942,2SA970..
2N38(A)	Ge-PNP	AF/HF,20V,8mA,0,05W,0,5MHz	?1a	USA	(AC125..126,AC151,ASY26..27)
2N380	Ge-PNP	=2N378:60V	23a$	USA,Mot	2N1535..38,2N1545..48,2N3615..18..
2N3800	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	Fch,Mot,Nsc	-
2N3801	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	-	-
2N3802	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	-	-
2N3803	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	-	-
2N3804(A)	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	-	-
2N3805(A)	Si-PNP	Dual,LN,60V,0,05A,0,36W,>100MHz	81bq	-	-
2N3806	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N3807	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N3808	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N3809	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N381	Ge-PNP	AF-Driver,50V,0,4A,0,225W,3MHz	2a&	USA,Mot	ASY77,2N1189..90
2N3810(A)	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N3811(A)	Si-PNP	Dual,LN,60V,0,05A,0,6W,>100MHz	81bs	-	2N4015..16
2N3812	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3813	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3814	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3815	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3816(A)	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3817(A)	Si-PNP	Dual,LN,60V,0,05A,0,35W,>100MHz	10-FLP/ch	-	-
2N3818	Si-NPN	VHF-Pow,60V,2A,Pq=15W(100MHz)	49a	Mot,Sca,Ssi	BLY35,2N3632
2N3819	N-FET	GenP/VHF,sym,25V,Idss>20mA,0.36W,Up<8V	7e	USA,EUR	BF244..245,BFS72,2N3823
2N382	Ge-PNP	=2N381:4MHz	2a&	-	ASY77,2N1189..90
2N3820	P-FET	GenP,sym,20V,15mA,0.36W,Idss>0,3mA,Up<8V	7e	USA,Phi,Tix	BF320A,J177,2N3909
2N3821	N-FET	GenP/VHF,50V,2.5mA,0.3W,Idss>0,5mA,Up<4V	5h+	USA,EUR	BFS70,2N4220,2N4340,2SK104,2SK301
2N3822	N-FET	GenP/VHF,50V,Idss>2mA,Up<6V	5h+	USA,EUR	BFS71,BFS80,BFW11,2N4341,2N4416
2N3823	N-FET	VHF,LN,30V,Idss>4mA,Up<8V	5h+	USA,EUR	2N4416,BF244..245,BFS72
2N3824	N-FET	Chopper,sym,50V,10mA,0.3W,<250Ω	5h+	USA,EUR	BFS73
2N3825	Si-NPN	GenP,30V,0,1A,0,25W,>200MHz	7c	Mic,Nsc,Tix	BC168,BC183,BC238,BC548..
2N3826	Si-NPN	AM/FM-Mix/Osc/IF,300MHz,B>40	7c	TI	BF240..241,BF254..255,BF594..595,..
2N3827	Si-NPN	=2N3826:B>100	7c	TI	BF240..241,BF254..255,BF594..595,..
2N3828	Si-NPN	TV-IF,40V,0,1A,0,3W,>360MHz	7c	Sem,Tix	BF198..199,BF224..225,BF596..597,..
2N3829	Si-PNP	Sw,35V,0,2A,0,36W,<25/65nS	2a$	Sca,Ssi,Tix	BSS10..11,BSX19..20,2N2368..69(A),..
2N383	Ge-PNP	=2N381:5MHz	2a&	-	ASY77,2N1189..90
2N3830	Si-NPN	Sw,80V,1,2A,1W,<60/70nS	2a$	USA,Tix	BSS14,BSV95,2N3735,2N5262
2N3831	Si-NPN	=2N3830:70V	2a$	USA,Tix	BSS14,BSV95,2N3735,2N5262
2N3832	Si-NPN	Sw,15V,0,035A,0,2W,<35/30nS	5g	Etc,Tix	BSS10..12,BSY17..18,2N3011..
2N3833	Si-NPN	UHF,25V,0,1A,>1GHz	24f	TI	BFT12,2SC3288,2SC3368..69
2N3834	Si-NPN	UHF,25V,0,1A,>1GHz	24f	TI	BFT12,2SC3288,2SC3368..69
2N3835	Si-NPN	UHF,25V,0,1A,>1GHz	24f	TI	BFT12,2SC3288,2SC3368..69
2N3836	Si-NPN-Darl	AF,Sw-Pow,80V,7A,25W,B>1000	-	TI	-
2N3837	Si-NPN-Darl	=2N3836:100V	-	TI	-
2N3838	Si-P/N	NPN+PNP,60V,0,6A,0,35W,>200MHz	10-FLP/ch	Mot,Ray,Tix	-
2N3839	Si-NPN	UHF-Pre-in/Mix/Osc,30V,0,04A,0,2W,>1GHz	5g	USA,Mot,Sgs	BF357,BF377..378,2SC2498,2SC3037,..

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2N384	Ge-PNP	AM/FM,40V,10mA,0,12W,70MHz	4g	Sty	AF106,AF124..125,AF200
2N384/33	Ge-PNP	=2N384:	5g	Syl	AF106,AF124..125,AF200
2N3840	Si-PNP	Chopper,50/50/50V,0,1A,0,4W	2a$	Sem,Spr,Tdy	2N2946
2N3841	Si-PNP	Chopper,100/100/80V,0,1A,0,3W	2a$	Sem,Sty	-
2N3842	Si-PNP	Chopper,120/120/120V,0,1A,0,3W	2a$	Sem,Sty	-
2N3843(A)	Si-NPN	HF-Pre/Mix//AF,30V,0,1A,0,2W,>60MHz	7c	USA,Gen,Mic	BF240..241,BF254..255,BF594..595,..
2N3844(A)	Si-NPN	HF-Pre/Mix//AF,30V,0,1A,0,2W,>90MHz	7c	USA,Gen,Mic	BF240..241,BF254..255,BF594..595,..
2N3845(A)	Si-NPN	HF-Pre/Mix/AF,30V,0,1A,0,2W,>120MHz	7c	USA,Gen,Mic	BF240..241,BF254..255,BF594..595,..
2N3846	Si-NPN	Sw,Pow,300/200V,20A,150W(Tc=100°)	49a$	USA,Tix	2N6324..25
2N3847	Si-NPN	=2N3846:400/300V	49a$	-	2N6325
2N3848	Si-NPN	Sw,Pow,300/200V,20A,150W(Tc=100°)	49a$	USA,Tix	2N6324..25
2N3849	Si-NPN	=2N3848:400/300V	49a$	-	2N6325
2N385	Ge-NPN	HF/Sw,25V,Ueb=15V,0,2A,0,15W,6MHz	2a	USA	ASY28..29,ASY73..75
2N3850	Si-NPN	Sw,Pow,100/80V,5A,40W(Tc=100°),B>50	49a$	USA,Tix	2N5002,2N5004,2N5284..85
2N3851	Si-NPN	=2N3850:B>30	49a$	-	2N5002,2N5004,2N5284..85
2N3852	Si-NPN	=2N3850:60V	49a$	-	2N5002,2N5004,2N5284..85
2N3853	Si-NPN	=2N3850:60V,B>30	49a$	-	2N5002,2N5004,2N5284..85
2N3854	Si-NPN	GenP,18V,0,1A,0,2W,>100MHz,B>35	7c	USA,Gen,Mic	BC168,BC183,BC238,BC548..
2N3854A	Si-NPN	=2N3854:30V	7c	-	BC168,BC183,BC238,BC548..
2N3855	Si-NPN	=2N3854:>130MHz,B>60	7c	-	BC168,BC183,BC238,BC548..
2N3855A	Si-NPN	=2N3855:30V	7c	-	BC168,BC183,BC238,BC548..
2N3856	Si-NPN	=2N3854:>140MHz,B>100	7c	-	BC168,BC183,BC238,BC548..
2N3856A	Si-NPN	=2N3856:30V	7c	-	BC168,BC183,BC238,BC548..
2N3857	Si-PNP	AF,45V,0,5A,0,6W,>20MHz	2a$	Sty	BC160..161,BC303..304,BC638..
2N3858	Si-NPN	GenP,30V,0,1A,0,36W,125MHz,B>60	7c	USA,Mic,++	BC168,BC183,BC238,BC548..
2N3858A	Si-NPN	=2N3858:60V	7c	-	BC174,BC182,BC190,BC546..
2N3859	Si-NPN	=2N3858:140MHz,B>100	7c	-	BC168,BC183,BC238,BC548..
2N3859A	Si-NPN	=2N3859:60V	7c	-	BC174,BC182,BC190,BC546..
2N385A	Ge-NPN	=2N385:40V,8MHz	2a	-	-
2N386	Ge-PNP	AF,Sw-Pow,60V,3A,12,5W(Tc=75°)	?23	Phc	AL102..103,AUY19..20,2N2144..46..
2N3860	Si-NPN	=2N3858:170MHz,B>150	7c	-	BC168,BC183,BC238,BC548..
2N3860A	Si-NPN	=2N3860:60V	7c	-	BC174,BC182,BC190,BC546..
2N3861	Si-NPN	Sw,Vid,530/530V,0,025A,>50MHz	43a$	USA	(BD232,BD410,BUX86..87,2SC2899)
2N3862	Si-NPN	Sw,50V,0,2A,0,36W,<78/50nS	5g	USA	BSX39,2N4014..14,2SC1834
2N3863	Si-NPN	Sw,Pow,70V,7,5A,117W,>0,5MHz	23a$	USA	BD313,BD545B,BDW51C,2N3055,2N5632..34..
2N3864	Si-NPN	=2N3863:110V	23a$	-	BD313,BD545D,BDW51C,2N3055,2N5632..34..
2N3865	Si-NPN	=2N3863:160V	23a$	-	BDX11,BDY54,BUV50,2N3442,2SD733..
2N3866(A)	Si-NPN	VHF/UHF-Osc/Dr,55V,0,4A,Pq>1W(400MHz)	2a$	USA,EUR	BFR97
2N3867	Si-PNP	AF,Sw,40V,3A,1W,>60MHz,<100/400nS	2a$	USA,Mot,Sgs	2N3719..20
2N3868	Si-PNP	=2N3867:60V	2a$	-	2N3720,BSS44
2N3869	Si-NPN	HF-Dr,40V,0,5A,>400MHz	2a	USA,Nec	BFS51,BFR98,BLW16,2SC2852..
2N387	Ge-PNP	AF,Sw-Pow,80V,3A,12,5W(Tc=75°)	?23	Phc	AL102..103,AUY20,2N2141,2N2146..
2N3870	Thy-50Hz	100V,22A(Tc=65°),Igt/Ih<40/<70mA	29b$	Gen,Mot,Rca	MCR3835-3,BStE4026M,MCR63-3
2N3871	Thy-50Hz	=2N3870:200V	29b$	-	MCR3835-4,BStE4026M,MCR63-4
2N3872	Thy-50Hz	=2N3870:400V	29b$	-	MCR3835-6,BStE4026M,MCR63-6
2N3873	Thy-50Hz	=2N3870:600V	29b$	-	MCR3835-8,BStE4040M,MCR63-8
2N3876	Si-NPN	AF,Sw-Pow,140V,10A,125W,>50MHz	-	Ssi,Trw	-
2N3877	Si-NPN	Nix,70V,0,05A,0,2W,160MHz	7c	USA,Mic,Nsc	BC546,BSS38,BSX21,2SC1890(A)..
2N3877A	Si-NPN	=2N3877:85V	7c	-	BC546,BSS38,BSX21,2SC1890(A)..
2N3878	Si-NPN	AF,Sw-Pow,120V,4A,35W,>40MHz	22a$	USA,Rca,Tix	BDV10..12,BDY79,2SD722(A,B)
2N3879	Si-NPN	AF,Sw-Pow,120V,7A,35W,>40MHz	22a$	USA,Rca,Tix	MJE15030
2N388	Ge-NPN	Sw,25V,0,2A,0,15W,17MHz,600/600nS	2a&	USA,Tix	ASY28..29,ASY73..75
2N3880	Si-NPN	UHF,30V,0,2W,>1200MHz	5g	USA,Fch,Sgs	BF357,BF377..378,BFR37,BFW99..
2N3881	Si-NPN	AF,60V,1A,0,6W,>70MHz	2a$	Idi,Sca,Ssi	BC140..141,2N1990,2N2102,2N2405..
2N3882	MOS-P-FET-e	GenP,30V,Idss>0,25mA,Up<3V	SI+	Ray	-
2N3883	Ge-PNP	Sw,25V,0,3A,0,3W,300MHz,36/68nS	2a$	Mot,Ssi	-
2N388A	Ge-NPN	=2N388:40V	2a&	-	-
2N389(A,/I)	Si-NPN	AF,Sw-Pow,60V,3A,85W,>1MHz	-	USA,Tix	2N1722..23,(BD241A,BD535,BD935,..)
2N3896	Thy-50Hz	100V,22A(Tc=65°),Igt/Ih<40/<70mA	21b$	USA,Mot,Rca .	MCR70-3,C228A,MCR3935-3,BStE4126M,..
2N3897	Thy-50Hz	=2N3896:200V	21b$	-	C228B,MCR3935-4,BStE4126M,C35B,..
2N3898	Thy-50Hz	=2N3896:400V	21b$	-	C228D,MCR3935-6,BStE4126M,C35D,..
2N3899	Thy-50Hz	=2N3896:600V	21b$	-	C228M,MCR3935-8,BStE4140M,C35M,..
2N39	Ge-PNP	AF/HF,30V,8mA,0,05W	?1a	Cbs	(AC125..126,AC151,ASY26..27)
2N3900(A)	Si-NPN	GenP,LN,18V,0,1A,0,36W,160MHz	7c	USA,Mic,Nsc	BC169,BC184,BC239,BC549..

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2N3901	Si-NPN	GenP,18V,0,1A,0,36W,200MHz	7c	USA,Mic,Nsc	BC168,BC183,BC238,BC548..
2N3902	Si-NPN	Sw,Pow,700/325V,2,5A,100W(Tc=75°)	23a$	USA,Mot,Tix	BUS11(A),BUX46(A),BUX48A,2SC3091
2N3903	Si-NPN	GenP,60V,0,2A,0,625W,>250MHz,B>50	7e	USA,EUR	BC174,BC182,BC190,BC546..
2N3904	Si-NPN	60V,0.2A,0.35W,300MHz,B>100	7e	-	BC174,BC182,BC190,BC546..
2N3904S	Si-NPN	-	3S	Kec	→2N3904S
2N3904U	Si-NPN	-	3S(2mm)	Kec	→2N3904U
2N3905	Si-PNP	GenP,40V,0,2A,0,625W,>200MHz,B>50	7e	USA,EUR	BC212,BC257,BC307,BC557..
2N3906	Si-PNP	40V,0.2A,0.35W,250MHz,B>100	7e	-	BC212,BC257,BC307,BC557..
2N3906S	Si-PNP	-	3S	Kec	→2N3906S
2N3906U	Si-NPN	-	3S(2mm)	Kec	→2N3906U
2N3907	Si-NPN	Dual,60V,0,03A,0,6W,>60MHz,B>60	81bs	USA,Mic,Nsc	BFY81,2N2919..20
2N3908	Si-NPN	=2N3907:B>100	81bs	-	BFY81,2N2919..20
2N3909(A)	P-FET	GenP,20V,Idss>0,3mA,0.3W,Up<8V	5g+	USA,Mot,Tix	BF320,2N3820,2N5800
2N391	Ge-PNP	AF,Sw-Pow,50V,5A	-	Del	-
2N3910	Si-PNP	Chopper,60/50/50V,0,2A,0,5W	2a$	USA	-
2N3911	Si-PNP	Chopper,60/40/40V,0,2A,0,5W	2a$	USA	-
2N3912	Si-PNP	Chopper,60/30/30V,0,2A,0,5W	2a$	USA	-
2N3913	Si-PNP	=2N3910:0,4W	2a$	-	-
2N3914	Si-PNP	=2N3911:0,4W	2a$	-	-
2N3915	Si-PNP	=2N3912:0,4W	2a$	-	-
2N3916	Si-NPN	Sw,Vid,150/150V,0,15A,5W,>50MHz	43a$	USA	(BF380,BF415,MJE340,2SC2376,..)
2N3917	Si-NPN	Sw,Pow,80V,2A,20W(Tc=45°),>80MHz,B>30	23a$	USA,Tix	2SC1195
2N3918	Si-NPN	=2N3917:B>100	23a$	-	2SC1195
2N3919	Si-NPN	Sw,Pow,120V,10A,15W(Tc=75°),>80MHz,B>40	23a$	USA,Tix	BUW70,BUY55,2SC2769
2N392	Ge-PNP	AF-Pow,60V,5A	23a$	USA	2N1535..38,2N1545..48,2N3615..18..
2N3920	Si-NPN	=2N3919:B>100	23a$	-	BUW70,BUY55,2SC2769
2N3921	N-FET	Dual,LN,50V,Idss>1mA,Up<3V	81bx	USA,Isi,Nsc	BFQ10..16,U401,2N3954..59
2N3922	N-FET	Dual,LN,50V,Idss>1mA,Up<3V	81bx	USA,Isi,Nsc	BFQ10..16,U401,2N3954..59
2N3923	Si-NPN	Vid,150V,0,05A,0,8W,>40MHz	2a$	USA,Fch	BF257..259,BF657..659,2N5058..59..
2N3924	Si-NPN	VHF-Dr/Out,36V,0,5A,Pq=4W(175MHz)	2a$	Mot,Phi,Sem	BFS22,BFW46,BLY33,MRF237
2N3925	Si-NPN	VHF-Dr/Out,36V,1A,Pq=5W(175MHz)	49a$	Mot	BLY55,BLY57,BLY78
2N3926	Si-NPN	VHF-Pow,36V,1,5A,Pq=7W(175MHz)	49a*	=2N3924	BLW35,BLY58
2N3927	Si-NPN	VHF-Pow,36V,3A,Pq=12W(175MHz)	49a*	=2N3924	BLY58
2N3928	Si-NPN	Sw,80V,3A,5W(Tc=25°),<35/75nS	2a$	Idi,Sol,Tix	2N3507
2N3929	Si-NPN	=2N3928:20W	49a$	-	-
2N393	Ge-PNP	HF/Sw,Chopper,6/6/6V,0,05A,50MHz	37d	Csr,Spr	-
2N3930	Si-PNP	Vid,180V,0,05A,0,4W,>40MHz	2a$	Fch,Sca,Sgs	BF436..437,BF491..493,2SA1370..71,..
2N3931	Si-PNP	=2N3930:0,7W	2a$	-	BFQ36..37,BFT44..45,2SB606..
2N3932	Si-NPN	VHF/UHF,30V,0,2W,>750MHz	5g	USA,Mic,Rca	BF377..378,BF689,BF763,2N2857..
2N3933	Si-NPN	VHF/UHF,40V,0,2W,>750MHz	5g	USA,Mic,Rca	BF377..378,BF689,BF763,2N2857..
2N3934	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Nsc,Tsc	BFQ10..16,2N3954..59
2N3935	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Nsc,Tsc	BFQ10..16,2N3954..59
2N3936	Thy-50Hz	100V,7A(Tc=80°),Igt/Ih<60/<110mA	21b$	Ssi,Tag,Tix	BTW42/600R,TAG9N400,TAG15-100..
2N3937	Thy-50Hz	=2N3936:200V	21b$	-	BTW42/600R,TAG9N400,TAG15-200..
2N3938	Thy-50Hz	=2N3936:300V	21b$	-	BTW42/600R,TAG9N400,TAG15-300..
2N3939	Thy-50Hz	=2N3936:400V	21b$	-	BTW42/600R,TAG9N400,TAG15-400..
2N394	Ge-PNP	HF/Sw,10/10/10V,0,2A,0,15W,>4MHz	2a&	USA	(ASY26..27,ASY48,ASY76..77)
2N3940	Thy-50Hz	=2N3936:500V	21b$	-	BTW42/600R,TAG9N600,TAG15-500..
2N3941	Si-NPN	Dual,60V,0,05A,0,75W,>200MHz	81bs	Sol,Sty	2N3409..11
2N3942	Si-NPN	Dual,60V,0,05A,0,75W,>200MHz	81bs	-	2N3409..11
2N3943	Si-NPN	Dual,60V,0,05A,0,75W,>200MHz	81bq	-	-
2N3944	Si-NPN	Dual,60V,0,05A,0,75W,>200MHz	81bq	-	-
2N3945	Si-NPN	GenP,70V,1A,5W(Tc=25°),>60MHz	2a$	USA,Mic,Nsc	BC140..141,2N1990,2N2102,2N2405..
2N3946	Si-NPN	AF,Sw,60V,0,2A,0,36W,<70/375nS,B>50	2a$	USA,Mic,Mot	BC182,BC546,2N2221..22(A)..
2N3947	Si-NPN	=2N3946:B>100	2a$	-	BC182,BC546,2N2221..22(A)..
2N3948	Si-NPN	UHF-A/Osc/Dr,36V,0,4A,Pq>1W(400MHz)	2a$	USA,Mot,Tix	BFS50,MRF629,2SC2762,2SC3185
2N394A	Ge-PNP	=2N394:30/15/20V	2a&	-	(ASY26,ASY48,ASY76..77)
2N395	Ge-PNP	Sw,30V,0,2A,0,15W,5MHz,760/-nS	2a&	USA,Tix	ASY26,ASY48,ASY76..77
2N3950	Si-NPN	AM/FM-Pow,65V,3,3A,Pq=50W(50MHz)	49a*	USA,Mot	-
2N3953	Si-NPN	UHF,15V,0,03A,0,2W,>1300MHz	5g	Sca,Ssi	BF377..378,BF698,BF763,2N2857..
2N3954(A)	N-FET	Dual,VHF,LN,50V,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22,2N5196
2N3955(A)	N-FET	Dual,VHF,LN,50V,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22,2N5196..17
2N3956	N-FET	Dual,VHF,LN,50V,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22,2N5199
2N3957	N-FET	Dual,VHF,LN,50V,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22,2N5199

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2N3958	N-FET	Dual,VHF,LN,50V,5mA,0.25W,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22
2N3959	Si-NPN	Fast-Sw,20V,0,03A,0,4W,5,4/4,9nS	2a$	USA,Mot	-
2N396(A)	Ge-PNP	Sw,30V,0,2A,0,15(A:0,2)W,9MHz	2a&	USA,Tix	A5Y26,A5Y48,A5Y76..77
2N3960	Si-NPN	Fast-Sw,20V,0,03A,0,4W,5,4/4,9nS	2a$	USA,Mot	-
2N3961	Si-NPN	VHF-Dr/Out,65V,1A,Pq=4W(175MHz)	49a$	USA,Mot	BLY60
2N3962	Si-PNP	AF,LN,60V,0,2A,0,36W,>40MHz	2a$	USA,EUR	2SA970,2SA1049,2SA1136..37
2N3963	Si-PNP	AF,LN,80V,0,2A,0,36W,>40MHz	2a$	USA,EUR	2SA970,2SA1049,2SA1136..37
2N3964	Si-PNP	AF,LN,45V,0,2A,0,36W,>50MHz	2a$	USA,EUR	BC416,BC560,2SA970,2SA1136..37..
2N3965	Si-PNP	AF,LN,60V,0,2A,0,36W,>50MHz	2a$	USA,EUR	2SA970,2SA1049,2SA1136..37
2N3966	N-FET	Sw,30V,Idss>2mA,Up<6V,<120/100nS	5h+	USA,EUR,Mic	BFS76,BFS79
2N3967(A)	N-FET	GenP,30V,Idss>2,5mA,Up<6V	5h+	USA,Nsc	BF256A,BFS71,2N3822,2N4221..
2N3968(A)	N-FET	GenP,30V,Idss>1mA,Up<3V	5h+	USA,Nsc	BFW12,2N4340,2N5484
2N3969(A)	N-FET	GenP,30V,Idss>0,4mA,Up<1,7V	5h+	USA,Nsc	2N4339,2N5358,2SK83,2SK195,2SK238
2N397	Ge-PNP	Sw,30V,0,2A,0,15W,13MHz,500/1000nS	2a&	USA,Tix	A5Y26,A5Y48,A5Y76..77
2N3970	N-FET	Sw,Chopper,40V,Idss>50mA,Up<10V	2b&	USA,Mot,Tix	BFS74,BFS77..78,2N4391,2N4856
2N3971	N-FET	Sw,Chopper,40V,Idss>25mA,Up<5V	2b&	USA,Mot,Tix	2N4392,2N5434
2N3972	N-FET	Sw,Chopper,40V,50mA,1.8W,Idss>5mA,Up<3V	2b&	USA,Mot,Tix	2N4393
2N3973	Si-NPN	AF,Sw,60V,0,4A,0,36W,<60/110nS	7c	Gen,Sem,Spr	BSV59,BSX49,2N2221..22(A),2N4014,..
2N3974	Si-NPN	AF,Sw,60V,0,4A,0,36W,<60/110nS	7c	Gen,Sem,Spr	BSV59,BSX49,2N2221..22(A),2N4014,..
2N3975	Si-NPN	AF,Sw,60V,0,4A,0,36W,<60/200nS	7c	Gen,Sem,Spr	BSV59,BSX49,2N2221..22(A),2N4014,..
2N3976	Si-NPN	AF,Sw,60V,0,4A,0,36W,<60/200nS	7c	Gen,Sem,Spr	BSV59,BSX49,2N2221..22(A),2N4014,..
2N3977	Si-PNP	Chopper,15/10/15V,0,1A,0,4W	2a$	Spr,Ssi	2N2944
2N3978	Si-PNP	Chopper,25/20/25V,0,1A,0,4W	2a$	USA,Mot	2N2945
2N3979	Si-PNP	Chopper,40/35/40V,0,1A,0,4W	2a$	Spr,Ssi,Tdy	2N2946
2N398	Ge-PNP	AF,Sw,105V,0,1A,0,05W,1MHz	2a	USA,Mot,Tix	ACY39,2N2042..43
2N3980	UJT-P	Ip<2µA,Iv>1mA	5r$	Mot,Tix	-
2N3981	Si-NPN	Sw,60V,1A,0,8W,<35/40nS	2a$	Nsc,Sty	BSS27,BSV77,BSV95,2N5189..+
2N3982	Si-NPN	=2N3981:50V	2a$	Nsc,Sty	BSS27,BSV77,BSV95,2N5189..+
2N3983	Si-NPN	VHF,30V,0,03A,0,2W,>500MHz	7c	Sem,Sty	BF225,BF310,BF314,BFS02,BF505..
2N3984	Si-NPN	VHF,30V,0,03A,0,2W,>400MHz	7c	Sem,Sty	BF225,BF310,BF314,BFS02,BF505..
2N3985	Si-NPN	VHF,30V,0,03A,0,2W,>300MHz	7c	Sem,Sty	BF225,BF310,BF314,BFS02,BF505..
2N398A	Ge-PNP	=2N398:0,2A,0,15W	2a	-	ACY39,2N2042..43
2N398B	Ge-PNP	=2N398:0,25W	2a	-	ACY39,2N2042..43
2N399	Ge-PNP	AF-Pow,-/40V,3A,45W(Tc=45°)	23a$	USA	AD149,AUY19..20,2N2143..46..
2N3993(A)	P-FET	Sw,Chopper,25V,Idss>10mA,Up<9,5V	5g+	USA,Mot,Tix	MPF970
2N3994(A)	P-FET	Sw,Chopper,25V,Idss>2mA,Up<5,5V	5g+	USA,Mot,Tix	MPF971
2N3995	Ge-PNP	VHF,20V,0,1A,0,3W,>600MHz	2a$	TI	2N2929
2N3996	Si-NPN	Sw,Pow,100V,5A,30W(Tc=100°),>40MHz	50g	USA,Tix	2N5002,2N5004,2N5284..85,2N5339
2N3997	Si-NPN	Sw,Pow,100V,5A,30W(Tc=100°),>40MHz	50g	USA,Tix	2N5002,2N5004,2N5284..85,2N5339
2N3998	Si-NPN	Sw,Pow,100V,5A,30W(Tc=100°),>40MHz	?49a$	USA,Tix	2N5002,2N5004,2N5284..85
2N3999	Si-NPN	Sw,Pow,100V,5A,30W(Tc=100°),>40MHz	?49a$	USA,Tix	2N5002,2N5004,2N5284..85,2N5339
2N40	Ge-PNP	AF/HF,30V,8mA,0,05W	?1a	Cbs	(AC125..126,AC151,A5Y26..27)
2N400	Ge-PNP	AF-Pow,50/40V,3A,45W(Tc=45°)	23a$	USA	AD149,AUY19..20,2N2143..46..
2N4000	Si-NPN	Sw,100V,1A,15W(Tc=100°),>40MHz	2a$	USA,Tix	BUX49,BUY41,2N5339
2N4001	Si-NPN	100V,1A,15W,40MHz	2a$	-	BUX49,BUY41,2N5339
2N4002	Si-NPN	Sw,Pow,100V,30A,100W(Tc=100°),>30MHz	49a$	USA,Tix	2N2824..25,BUV20
2N4003	Si-NPN	=2N4002:120V	49a$	-	2N2825
2N4004	Si-NPN	Sw,Pow,100V,20A,40W(Tc=100°),>30MHz	-	USA,Tix	2N3263..64
2N4005	Si-NPN	=2N4004:120V	-		2N3263..64
2N4006	Si-PNP	Chopper,10/6/10V,0,1A,0,4W	2a$	Spr,Ssi,Tdy	2N2944
2N4007	Si-PNP	Chopper,20/15/20V,0,1A,0,4W	2a$	Spr,Ssi,Tdy	2N2945
2N4008	Si-PNP	Chopper,35/30/35V,0,1A,0,4W	2a$	Spr,Ssi,Tdy	2N2946
2N4009	Si-PNP	=2N4006:gep	2a$	-	2N2944
2N401	Ge-PNP	AF-Pow,-/40V,3A,45W(Tc=45°)	23a$	USA	AD149,AUY19..20,2N2143..46..
2N4010	Si-PNP	=2N4007:gep	2a$	-	2N2945
2N4011	Si-PNP	=2N4008:gep	2a$	-	2N2946
2N4012	Si-NPN	VHF/UHF-Pow,65V,1,5A,Pq=3W(800MHz)	49a	USA,Mot,Rca	-
2N4013	Si-NPN	Sw,50V,1A,0,36W,20/55nS	2a$	USA,Mot,Tix	2N3736..37
2N4014	Si-NPN	=2N4013:80V,20/50nS	2a$	-	2N3737
2N4015	Si-PNP	Dual,LN,60V,0,3A,0,5W,>200MHz	81bs	Fch,Mic,Mot	-
2N4016	Si-PNP	Dual,LN,60V,0,3A,0,5W,>200MHz	81bs	-	-
2N4017	Si-PNP	Dual,LN,80V,0,2A,0,6W,>40MHz	81bs	Fch,Mic,Nsc	-
2N4018	Si-PNP	Dual,LN,60V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4019	Si-PNP	Dual,LN,45V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16

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2N402	Ge-PNP	AF,25V,0,15A,0,18W,0,6MHz,B=25	2a	USA	AC125..126,AC151,2SB54,2SB56
2N4020	Si-PNP	Dual,LN,45V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4021	Si-PNP	Dual,LN,60V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4022	Si-PNP	Dual,LN,60V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4023	Si-PNP	Dual,LN,45V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4024	Si-PNP	Dual,LN,60V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4025	Si-PNP	Dual,LN,60V,0,2A,0,6W,>40MHz	81bs	-	2N4015..16
2N4026	Si-PNP	Sw,60V,1A,0,5W,<100/400ns,B>40	2a$	USA,Mic,Mot	BC327A,BC638,BC640,2N2906..07(A)..
2N4027	Si-PNP	=2N4026:80V	2a$	-	BC640,BCX39,2SB647,2N2906..07A..
2N4028	Si-PNP	=2N4026:B>100	2a$	-	BC327A,BC638,BC640,2N2906..07(A)..
2N4029	Si-PNP	=2N4026:80V,B>100	2a$	-	BC640,BCX39,2SB647,2N2906..07A..
2N403	Ge-PNP	=2N402:B=33	2a	USA	AC125..126,AC151,2SB54,2SB56
2N4030	Si-PNP	=2N4026:0,8W	2a$	-	BC161,BCX60,BSW40,2N2904..05(A),..
2N4031	Si-PNP	=2N4027:0,8W	2a$	-	BCX60,BSW40,2N2904..05A,2N4036
2N4032	Si-PNP	=2N4028:0,8W	2a$	-	BC161,BCX60,BSW40,2N2904..05(A),..
2N4033	Si-PNP	80V,1A,0.8W,150MHz	2a$	-	BCX60,BSW40,2N2904..05A,2N4036
2N4034	Si-PNP	HF/Sw,40V,0,1A,0,36W,<40/150nS,B>70	2a$	USA,Sgs	BFX48,BSW24,BSX36,2N3250..51(A)
2N4035	Si-PNP	=2N4034:B>150	2a$	-	BFX48,BSW24,BSX36,2N3250..51(A)
2N4036	Si-PNP	AF,Sw,90V,1A,1W,60MHz,<110/700nS	2a$	USA,EUR	BCX60,BFR23,BSW40
2N4037	Si-PNP	AF,Sw,60V,1A,1W,>60MHz	2a$	USA,EUR	BC161,BCX60,BFR24,BSW40..
2N4038	MOS-N-FET-d	GenP,50V,Idss<0,1mA,Up<2V	5g+	Gie,Trw	-
2N4039	MOS-N-FET-d	GenP,50V,Idss>0,1mA,Up<6V	5g+	Gie,Trw	-
2N404	Ge-PNP	Sw,25V,Ueb=12V,0,15A,0,15W,190/300nS	2a	USA,Mot,Tix	ASY26..27,ASY48,ASY76..77
2N4040	Si-NPN	UHF-Pow,65V,3A,Pq>8W(400MHz)	55r	USA,Fer,Tix	BLW94,BLX94..95,MRF323,2SC1118
2N4041	Si-NPN	UHF-Pow,65V,1A,Pq>3,3W(400MHz)	55r	USA,Fer,Tix	BLW93,BLX93,MRF321,2SC1040
2N4042	Si-NPN	Dual,LN,60V,0,01A,0,5W,>200MHz	81bs	Sol,Sty	-
2N4043	Si-NPN	Dual,LN,45V,0,01A,0,5W,>150MHz	81bs	-	-
2N4044	Si-NPN	=2N4042:0,75W	81bs	-	-
2N4045	Si-NPN	=2N4043:0,75W	81bs	-	-
2N4046	Si-NPN	Sw,50V,0,5A,0,8W,<45/75nS	2a$	USA,Sgs,Nsc	BSS27..29,BSV77,2N3724,2SC1385..
2N4047	Si-NPN	=2N4046:80V,45/100nS	2a$	-	BSV95,2N3722..23,2N3725,2SC1069..
2N4048	Ge-PNP	Sw,Pow,45V,60A,170W,B>60	38a$	Gpd,Mot,Stc	MP500,MP504
2N4049	Ge-PNP	=2N4048:60V	38a$	-	MP501,MP505
2N404A	Ge-PNP	=2N404:40V,Ueb=25V	2a	-	-
2N405	Ge-PNP	AF,20V,35mA,0,15W,0,65MHz	1a	USA	AC125..126,AC151,2SB54,2SB56
2N4050	Ge-PNP	=2N4048:75V	38a$	-	MP502,MP506
2N4051	Ge-PNP	=2N4048:B>120	38a$	-	MP500,MP504
2N4052	Ge-PNP	=2N4048:60V,B>120	38a$	-	MP501,MP505
2N4053	Ge-PNP	=2N4048:75V,B>120	38a$	-	MP502,MP506
2N4054	Si-NPN	Vid,300V,0,1A,4W(Tc=75°),>15MHz	13h$	GE	BF617,BF758..759,BF859
2N4055	Si-NPN	=2N4054:250V	13h$	-	BF615,BF617,BF757..759,BF858..859
2N4056	Si-NPN	=2N4054:200V	13h$	-	BF615,BF617,BF757..759,BF858..859
2N4057	Si-NPN	=2N4054:150V	13h$	-	BF615,BF617,BF757..759,BF858..859
2N4058	Si-PNP	AF-Pre,LN,30V,0,03A,0,36W	7c	USA,Tix,++	BC214,BC259,BC309,BC559..
2N4059	Si-PNP	AF,30V,0,03A,0,36W,B>45	7c	USA,Tix,++	BC213,BC258,BC308,BC558..
2N406	Ge-PNP	=2N405:	2a	USA	AC125..126,AC151,2SB54,2SB56
2N4061	Si-PNP	=2N4060:B>90	7c	-	BC213,BC258,BC308,BC558..
2N4062	Si-PNP	=2N4060:B>180	7c	-	BC213,BC258,BC308,BC558..
2N4063	Si-NPN	=2N3439:10W	43a$	USA,Rca	(BD410,2SC3051,2SC3425)
2N4064	Si-NPN	=2N3440:10W	43a$	USA,Rca	(BD410,BF468,BF668,2SC3051,..)
2N4065	MOS-P-FET-e	HF/Sw,30V,Idss<12mA,Up<6V	5n+	Fch,Gie	-
2N4066	MOS-P-FET-e	Dual,Chopper,30V,0,2A,Up<6V	81bz	Gie,Mot	-
2N4067	MOS-P-FET-e	Dual,Chopper,30V,0,2A,Up<6V	81bz	Gie,Mot	-
2N4068	Si-NPN	Vid,150V,0,2A,0,5W,>50MHz	2a	Spe,Ssi	BF257..259,BF657..659,2N5058..59..
2N4069	Si-NPN	=2N4068:1W	2a$o	-	BF257..259,BF657..659,2N5058..59..
2N407	Ge-PNP	HF,20V,70mA,0,15W,6,8MHz	1a	USA	ASY26..27
2N4070	Si-NPN	Sw,Pow,120/100V,10A,115W,>20MHz	23a$	USA	BUW70,BUY55..56,BUX17
2N4071	Si-NPN	=2N4070:200V	23a$	-	BUW70,BUY55..56,BUX17
2N4072	Si-NPN	VHF-Dr,40V,0,1A,Pq>0,25W(175MHz)	2a$	USA,Mot	BFX59,2SC2053
2N4073	Si-NPN	VHF-Dr,40V,0,15A,Pq>0,5W(175MHz)	2a$	USA,Mot	BFR36,BFW16,MRF207,MRF607
2N4074	Si-NPN	GenP,40V,0,3A,0,4W,>50MHz	2a	USA	BC337,BC635,BC637,BC639..
2N4075	Si-NPN	Sw,Pow,100V,2A,30W,>30MHz,B>30	49a	USA,Fch,Phi	2N5002,2N5004,2N5284..85
2N4076	Si-NPN	=2N4076:B>50	49a	-	2N5002,2N5004,2N5284..85
2N4077	Ge-NPN	AF-Pow,32V,1A,7,5W(Tc=50°)	23a$	Amp,Phi,Spe	(AD161)

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2N4078	Ge-PNP	AF-Pow,32V,1A,7,5W(Tc=50°)	23a$	Amp,Phi,Spe	(AD162)
2N4079	Ge-P/N	=2N4077+4078gep	23a$	Amp,Phi,Spe	(AD161+162)
2N408	Ge-PNP	=2N407:	2a	USA	ASY26..27
2N4080	Si-PNP	UHF,20V,0,05A,0,3W,>1GHz	5g	Idi,Sca,Sem	BF316,BF439,BFS16,BF606..
2N4081	Si-NPN	VHF,LN,40V,0,2W,>600MHz	5k	Rca	BF314,BFS02,BFS05,BFS07,BFS62..
2N4082	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Isi,Sol,Nsc	BFQ10..16,2N3954..58
2N4083	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Isi,Sol,Nsc	BFQ10..16,2N3954..58
2N4084	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Isi,Sol,Nsc	BFQ10..16,U401,2N3954..58
2N4085	N-FET	Dual,LN,50V,Idss>0,3mA,Up<3V	81bx	Isi,Sol,Nsc	BFQ10..16,U404,2N3954..58
2N4086	Si-NPN	GenP,12V,0,1A,0,2W,B>150	7c	Gen,Sty	BC168,BC183,BC238,BC548..
2N4087(A)	Si-NPN	=2N4086:B>250	7c	-	BC168,BC183,BC238,BC548..
2N4088	P-FET	GenP,30V,Idss>5mA,Up<8V	5h+	Tsc	BF320B,2N5462,2N5465
2N4089	P-FET	GenP,30V,Idss>2mA,Up<5V	5h+	Tsc	2SJ104,2SJ107,2SJ108
2N409	Ge-PNP	HF,13V,15mA,0,08W,6,8MHz	1a	USA	AF124..127,AF200
2N4090	P-FET	GenP,30V,Idss>0,4mA,Up<3V	5h+	Tsc	2N2844
2N4091(A)	N-FET	Sw,Chopper,40..50V,Idss>30mA,Up<10V	2b&	USA,EUR	BFS74,BFS77,2N4856,2N4859,2N4391
2N4092(A)	N-FET	Sw,Chopper,40..50V,Idss>15mA,Up<7V	2b&	USA,EUR	BFS75,BFS77,2N4857,2N4860,2N4392
2N4093(A)	N-FET	Sw,Chopper,40..50V,Idss>8mA,Up<5V	2b&	USA,EUR	BFS75,BFS77,2N4857,2N4860,2N439..93
2N4094	N-FET	Sw,40V,Idss>75mA,25/40nS	2b&	Tsc	2N4391,2N5433
2N4095	N-FET	Sw,40V,Idss>20mA,35/60nS	2b&	Tsc	BFS75,BFS78,BSV79,2N4392,2N4857,2N4860
2N4096	Thy-50Hz	50V,0,4A(Tc=85°),Igt/Ih<0,2/<2mA	2a$	Fch,Sem,Uni	BRY58/60,(2N2323,2N6333,TAG615-100)
2N4097	Thy-50Hz	=2N4096:100V	2a$	-	BRY58/100,(2N2324,2N6334,TAG615-100)
2N4098	Thy-50Hz	=2N4096:200V	2a$	-	BRY58/200,(2N2326,2N6335,TAG615-200)
2N4099	Si-NPN	Dual,LN,55V,0,01A,0,5W,>150MHz	81bs	Sol,Sty	-
2N41	Ge-PNP	AF/HF,25V,15mA,0,05W	-	Rca	(AC125..126,AC151,ASY26..27)
2N410	Ge-PNP	=2N409:	2a	USA	AF124..127,AF200
2N4100	Si-NPN	=2N4099:0,75W	81bs	-	-
2N4101	Thy-50Hz	=2N3228:600V	22a$	Rca,Sgs,Tag	BStC0540L,TAG671-600,TAG676-600
2N4102	Thy-50Hz	600V,1,3A(Tc=75°),Igt/Ih<15/<20mA	2a$	Rca	TAG612-600,TAG613-600,TAG606-600,..
2N4103	Thy-50Hz	=2N3668:600V	23a$	Rca	2N2579
2N4104	Si-NPN	GenP,LN,60V,0,05A,0,3W,>60MHz	2a$	Idi,Sca,Tix	2N2483..84,2N3117,2SC2240,2SC2459..
2N4105	Ge-NPN	AF,25V,1A	2a	USA,Phi	AC176,AC187
2N4106	Ge-PNP	AF,25V,1A,1,6W	2a	USA,Phi	AC128,AC153,AC188
2N4107	Ge-P/N	AF,25V,1A	2a	USA,Phi	AC153+176,AC187+188
2N4108	Thy-50Hz	=2N4096	2a$	USA,Fch,Tag	→2N4096
2N4109	Thy-50Hz	=2N4096	2a$	USA,Fch,Tag	→2N4096
2N411	Ge-PNP	HF,13V,15mA,0,08W,16MHz	1a	USA	AF124..127,AF200
2N4110	Thy-50Hz	=2N4096	2a$	USA,Fch,Tag	→2N4096
2N4111	Si-NPN	Sw,Pow,100V,5A,30W(Tc=50°),>50MHz,B>40	23a$	USA	BDW51C,BDY90..91
2N4112	Si-NPN	=2N4111:B>100	23a$	-	BDY90..91
2N4113	Si-NPN	=2N4111:120V	23a$	-	BDW51C,BDY90
2N4114	Si-NPN	=2N4111:120V,B>100	23a$	-	BDY90
2N4115	Si-NPN	Sw,Pow,120V,5A,37W(Tc=100°),>50MHz	49a	USA	2N5284..85,2N5339
2N4116	Si-NPN	Sw,Pow,120V,5A,37W(Tc=100°),>70MHz	49a$	USA	2N5284..85,2N5339
2N4117(A)	N-FET	GenP,40V,Idss>0,02mA,Up<1,8V	5h+	USA,Mot,Tho	2SK92..93,2SK103
2N4118(A)	N-FET	GenP,40V,Idss>0,08mA,Up<3V	5h+	USA,Mot,Tho	2N3367,2N3370
2N4119(A)	N-FET	GenP,40V,Idss>0,2mA,Up<6V	5h+	USA,Mot,Tho	2N3366
2N412	Ge-PNP	=2N411:	2a	USA	AF124..127,AF200
2N4120	MOS-P-FET-e	Sw,30V,Idss>0,5nA,Up<6V	5n+	Fch,Gie	3N163
2N4121	Si-PNP	GenP,40V,0,1A,0,2W,<45/180nS,B>70	8a	USA,Mic,Sgs	BFX48,BSW24,BSX36,2N3905..06..
2N4122	Si-PNP	=2N4122:B>150	8a	-	-
2N4123	Si-NPN	AF,Sw,40V,0,2A,0,625W,37/136nS	7e	USA,Fer,Mot	BC237,BC547,BSW41,2N2221..22(A),..
2N4124	Si-NPN	AF,Sw,30V,0,2A,0,625W,37/136nS	7e	-	BC238,BC548,BSW41,2N2221..22(A),..
2N4125	Si-PNP	AF,Sw,30V,0,2A,0,625W,43/155nS	7e	USA,Fer,Mot	BC308,BC558,BSW24,2N2906..07(A),..
2N4126	Si-PNP	AF,Sw,25V,0,2A,0,625W,43/155nS	7e	-	BC308,BC558,BSW24,2N2906..07(A),..
2N4127	Si-NPN	VHF-Pow,60V,2A,Pq>13,5W(175MHz)	55r	USA,Fer,Tix	BLW24,BLY92..93,2SC2887
2N4128	Si-NPN	VHF-Pow,60V,4A,Pq>24W(175MHz)	55r	USA,Fer,Tix	MRF314A,2SC2888
2N413(A)	Ge-PNP	AF/HF,30V,Ueb=20V,0,4A,0,2W	2a	USA	ASY76..77
2N4130	Si-NPN	AM/FM-Pow,80V,10A,Pq=50W(70MHz)	23a$	Motorola	-
2N4131	Si-NPN	HF-Pow,90V,5A,60W,>150MHz	23e*	Ker,Sca,Ssi	-
2N4132	Si-NPN	HF-Pow,90V,0,6A,7,5W,>200MHz	43a*	Ker,Sca,Ssi	-
2N4133	Si-NPN	HF,90V,0,6A,>200MHz	2a*	Ker,Sca,Ssi	-
2N4134	Si-NPN	VHF/UHF/IF,30V,0,03A,0,2W,>350MHz	5g	USA,Nsc,Sgs	BF314,BFS02,BFS05,BFS07,BFS62..
2N4135	Si-NPN	VHF/UHF/IF,30V,0,03A,0,2W,>425MHz	5g	USA,Nsc,Sgs	BF314,BFS02,BFS05,BFS07,BFS62..

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2N4136	Ge-P/N	=2N2430+2431gep	-	Amp,Phc	-
2N4137	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<15/20nS	2a$	USA,Sgs	BS510..11,BSX19..20,2N2368..69(A),..
2N4138	Si-NPN	Chopper,30V,0,1A,0,3W,>20MHz	2a$	Tdy,Tix	2N2432
2N4139	N-FET	GenP,LN,50V,Idss>8mA,Up<8V	2b&	USA,Mic	BFW10,2N5363
2N414(A,B,C)	Ge-PNP	AF/HF,30V,Ueb=20V,0,4A,0,2W,7MHz	2a	USA	ASY76..77
2N4140	Si-NPN	GenP,60V,0,2A,0,3W,<50/310nS,B>40	8a	USA,Mic,Nsc	BC337A,BC637,BSV59,2N2221..22(A)..
2N4141	Si-NPN	=2N4140:B>100	8a	-	BC337A,BC637,BSV59,2N2221..22(A)..
2N4142	Si-PNP	GenP,60V,0,2A,0,3W,<50/110nS,B>40	8a	USA,Mic,Nsc	BC327A,BC638,BSW24,2N2906..07(A)..
2N4143	SI-PNP	=2N4142:B>100	8a	-	BC327A,BC638,BSW24,2N2906..07(A)..
2N4144	Thy-50Hz	15V,0,25A(Tc=75°),Igt/Ih<1/<5mA	2a$	Sem,Tra,Uni	(2N1595A,TAG2-50,MCR1906-3,..)
2N4145	Thy-50Hz	=2N4144:30V	2a$	-	(2N1595A,TAG2-50,MCR1906-3,..)
2N4146	Thy-50Hz	=2N4144:60V	2a$	-	(2N1596A,TAG2-100,MCR1906-3,..)
2N4147	Thy-50Hz	=2N4144:100V	2a$	-	(2N1596A,TAG2-100,MCR1906-3,..)
2N4148	Thy-50Hz	=2N4144:150V	2a$	-	(2N1597A,TAG2-200,MCR1906-4,..)
2N4149	Thy-50Hz	=2N4144:200V	2a$	-	(2N1597A,TAG2-200,MCR1906-4,..)
2N415(A)	Ge-PNP	AF/HF,30V,Ueb=20V,0,4A,0,2W,10MHz	2a	USA	ASY76..77
2N4150	Si-NPN	Sw,Pow,100V,5A,8,75W(Tc=25°),>15MHz	2a$	USA,Sgs	BFT33..34,BUX34,BUY80,2N5338..39
2N416	Ge-PNP	AF/HF,30V,Ueb=20V,0,4A,0,2W,10MHz	2a	USA	ASY76..77
2N417	Ge-PNP	AF/HF,30V,Ueb=20V,0,4A,0,2W,20MHz	2a	USA	ASY76..77
2N418	Ge-PNP	Sw,Pow,100V,5A,25W(Tc=45°),0,4MHz	23a$	USA	AL102..103,AUY28,2N1542..43..
2N419	Ge-PNP	Sw,Pow,55V,3A,25W(Tc=45°),0,3MHz	23a$	USA	AD149,AUY19..20,2N2144..46..
2N4199	Thy-Fast	300V,5A(Tc=65°),Igt/Ih<50/3mA,<20µS	21b$	Mot,Ssi	(T6F300C,TAG15S-400,C234D,MCR1718-5)
2N42	Ge-PNP	AF/HF,30V,8mA,0,05W,36MHz	?1a	Cbs	(AC125..126,AC151,ASY26..27)
2N420	Ge-PNP	Sw,Pow,65V,5A,25W(Tc=45°),0,4MHz	23a$	USA	AL102..103,AUY28,2N1546..48..
2N4200	Thy-Fast	=2N4199:400V	21b$	-	(T6F400C,TAG15S-400,C234D,MCR1718-6)
2N4201	Thy-Fast	=2N4199:500V	21b$	-	(T6F500C,TAG15S-500,C234E,MCR1718-7)
2N4202	Thy-Fast	=2N4199:600V	21b$	-	(T6F600C,TAG15S-600,C234M,MCR1718-8)
2N4203	Thy-Fast	=2N4199:700V	21b$	-	(T6F700C,TAG15S-700,T12F700,2N691S)
2N4204	Thy-Fast	=2N4199:800V	21b$	-	(T6F800C,TAG15S-800,T12F800,2N692S)
2N4205	Thy-Fast	=2N4199:900V	21b$	-	(TAG15S-900,T12F900,TAG35S-900)
2N4206	Thy-Fast	=2N4199:1000V	21b$	-	(TAG15S-1000,T12F1000,TAG35S-1000)
2N4207	Si-PNP	Sw,6V,0,05A,0,35W,<25/25nS	2a$	USA,Sgs	BSX36
2N4208	Si-PNP	Sw,12V,0,05A,0,35W,<25/30nS	2a$	USA,Mot,Sgs	BSX36
2N4209	Si-PNP	Sw,15V,0,05A,0,35W,<25/30nS	2a$	USA,Mot,Sgs	BSX36
2N420A	Ge-PNP	=2N420:90V	23a$	-	AL102..103,AUY28,2N1547..48..
2N421	Ge-PNP	AF,Sw-Pow,65V,5A,0,4MHz	-	Ben	-
2N4210	Si-NPN	Sw,Pow,80/60V,20A,100W(Tc=60°),>10MHz	49a$	USA,Tix	2N2815..22
2N4211	Si-NPN	=2N4210:100/80V	49a$	-	2N2815..18,2N2820..22
2N4212	Thy-50Hz	25V,1,6A,Igt/Ih<0,1/3mA	2a$	Mot,Sgs,Tag	2N2322,2N6332,TAG615-100,(MCR606-2)
2N4213	Thy-50Hz	=2N4212:50V	2a$	-	2N2323,2N6333,TAG615-100,(MCR606-2)
2N4214	Thy-50Hz	=2N4212:100V	2a$	-	2N2324,2N6334,TAG615-100,(MCR606-3)
2N4215	Thy-50Hz	=2N4212:150V	2a$	-	2N2325,2N6335,TAG615-200,(MCR606-4)
2N4216	Thy-50Hz	=2N4212:200V	2a$	-	2N2326,2N6335,TAG615-200,(MCR606-4)
2N4217	Thy-50Hz	=2N4212:250V	2a$	-	2N2327,2N6336,TAG615-300,(MCR606-5)
2N4218	Thy-50Hz	=2N4212:300V	2a$	-	2N2328,2N6336,TAG615-300,(MCR606-5)
2N4219	Thy-50Hz	=2N4212:400V	2a$	-	2N2329,2N6337,TAG615-400,(MCR606-6)
2N422	Ge-PNP	AF,35V,Ueb=12V,0,1A,0,15W,0,8MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N4220(A)	N-FET	GenP,sym,30V,Idss>0,5mA,Up<4V	5m+	USA,EUR	BFS70,2N3821,2SK104,2SK301
2N4221(A)	N-FET	GenP,sym,30V,Idss>2mA,Up<6V	5m+	USA,EUR	BFS71,2N3822,2N4341,2N5361,2N5458
2N4222(A)	N-FET	GenP,sym,30V,Idss>5mA,Up<8V	5m+	USA,EUR	BF244..245,BFS72,2N3823,2N5459
2N4223	N-FET	VHF-Pre/Mix,sym,30V,Idss>3mA,Up<8V	5m+	USA,Mot,Tix	2N4416,BF244..245
2N4224	N-FET	VHF-Pre/Mix,sym,30V,Idss>2mA,Up<8V	5m+	USA,Mot,Tix	2N4416,BF244..245
2N4225	Si-NPN	Sw,80V,3A,5W(Tc=25°),<35/75nS	2a$	Ker,Sol,Ssi	2N3507
2N4226	Si-NPN	=2N4225:100V	2a$	-	-
2N4227	Si-NPN	AF-Driver,60V,0,2A,0,3W,<50/310nS	8a	Idi,Nsc,Sem	BC337A,BC637,BSV59,2N2221..22(A)..
2N4228	Si-PNP	AF-Driver,60V,0,2A,0,3W,<50/110nS	8a	Idi,Nsc,Sem	BC327A,BC638,BSW24,2N2906..07(A)..
2N422A	Ge-PNP	=2N422:0,2A,0,185W,>1,5MHz	2a	-	AC125..126,AC151,2SB54,2SB56
2N4231	Si-NPN	AF,Sw-Pow,50V,3A,35W,>4MHz	22a$	USA,Mot,Tix	BD241,BD535,BD539A,2N3054..
2N4231A	Si-NPN	=2N4231:5A,75W	22a$	-	BD243,BD949,BD539A,2N3054..
2N4232	Si-NPN	=2N4231:70V	22a$	-	BD241A,BD537,BD539B,2N3054..
2N4232A	Si-NPN	=2N4231:5A,75W	22a$	-	BD243A,BD951,BD539B,2N3054..
2N4233	Si-NPN	=2N4231:90V	22a$	-	BD241B,BD937,BD539C,2N3054..
2N4233A	Si-NPN	=2N4231:90V	22a$	-	BD243B,BD953,BD539C,2N3054..
2N4234	Si-PNP	AF,Sw,40V,3A,1W,>3MHz	2a$	USA,Mot,Mic	BFT35..37,BSS46,2N6190..93

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2N4235	Si-PNP	=2N4234:60V	2a$	-	BFT35..37,BSS46,2N6190..93
2N4236	Si-PNP	80V,3A,1W,>3MHz	2a$	-	BFT35..37,BSS46,2N6190..93
2N4237	Si-NPN	AF,Sw,50V,3A,1W,>2MHz	2a$	=2N4234	BFT32..34,BSS63..64,2N5336..39
2N4238	Si-NPN	=2N4237:80V	2a$	-	BFT32..34,BSX63..64,2N5336..39
2N4239	Si-NPN	=2N4238:100V	2a$	-	BFT33..34,BSX64,2N5338..39,2SC2214
2N424(A,/I)	Si-NPN	AF,Sw-Pow,-/80V,3A,85W,1MHz	-	USA,Tix	2N1722..23,(BD241B,BDS37,BD937,..)
2N4240	Si-NPN	Sw,Pow,500/300V,2A,35W,>15MHz	22a$	Mot,Rca,Sem	BUW40A,B,BUX84,2N3585,2SC3169..
2N4241(MP)	Ge-PNP	AF-Pow,32,5A,37W	23a$	USA	AL102..103,AUY28,2N3611..18..
2N4242	Ge-PNP	AF,Sw-Pow,80,10A,106W,B>40	23a$	Csr,Sem	2N1559..60,2N2289..90,2N2292..93..
2N4243	Ge-PNP	=2N4242:60V	23a$	-	2N1558..60,2N2289..90,2N2292..93..
2N4244	Ge-PNP	=2N4242:40V	23a$	-	2N1557..60,2N2288..90,2N2291..93..
2N4245	Ge-PNP	=2N4242:B>60	23a$	-	2N1559..60,2N2289..90,2N2292..93..
2N4246	Ge-PNP	=2N4242:60V,B>60	23a$	-	2N1558..60,2N2289..90,2N2292..93..
2N4247	Ge-PNP	=2N4242:40V,B>60	23a$	-	2N1557..60,2N2288..90,2N2291..93..
2N4248	Si-PNP	GenP,40V,0,1A,0,2W,B>50	8a	USA,Mic,Sgs	BC415..416,BC560,2SA970,2SA1137..
2N4249	Si-PNP	=2N4248:60V,B>100	8a	-	2SA970,2SA1049,2SA1136..37
2N425	Ge-PNP	AF,Sw,30V,Ueb=20V,0,4A,0,15W,B>20	2a	USA,Tix	ASY76..77
2N4250	Si-PNP	=2N4248:B>250	8a	-	BC415..416,BC560,2SA970,2SA1137..
2N4250A	Si-PNP	=2N4248:60V,B>250	8a	-	2SA970,2SA1049,2SA1136..37
2N4251	Si-NPN	Fast-Sw,RadH,15V,0,1A,0,25W,<20/60nS	2a$	Fch,Ssi	-
2N4252	Si-NPN	AM/FM-Pre/Mix/Osc,30V,0,05A,>600MHz,B>50	5g	USA,Tix	BF240..241,BF254..255,BF594..595,..
2N4253	Si-NPN	=2N4252:B>30	5g	-	BF240..241,BF254..255,BF594..595,..
2N4254	Si-NPN	=2N4252:0,25W	7c	-	BF240..241,BF254..255,BF594..595,..
2N4255	Si-NPN	=2N4252:0,25W,B>30	7c	-	BF240..241,BF254..255,BF594..595,..
2N4256	Si-NPN	Sw,30V,0,1A,0,36W,200MHz,4/40nS	7c	Gen,Sem,Spr	BSS11..12,BSX19..20,2N2368..69(A),..
2N4257(A)	Si-PNP	Sw,6V,0,05A,0,2W,>500MHz	8a	USA,Nsc,Sgs	BSX36
2N4258(A)	Si-PNP	Sw,12V,0,05A,0,2W,>700MHz	8a	USA,Nsc,Sgs	BSX36
2N4259	Si-NPN	UHF,40V,0,175W,1GHz	5g	USA,Nsc,Rca	BF377..378,BF689,BF763,2N2857..
2N426	Ge-PNP	=2N425:B>30,6MHz	2a	USA,Tix	ASY76..77
2N4260	Si-PNP	Fast-Sw,15V,0,03A,0,2W,>1,6GHz,1,5/2nS	5g	USA,Mot,Tix	-
2N4261	Si-PNP	=2N4260:>2GHz	5g	-	-
2N4262	Si-NPN	HF-Dr/Out,25V,0,2A,>900MHz	49a$	Mot,Sty	-
2N4263	Si-NPN	=2N4262	49a$	-	-
2N4264	Si-NPN	Sw,30V,0,2A,0,625W,<23/35nS,B>40	7e	Fch,Mot,Spr	BSS10..11,BSX19..20,2N2368..69(A),..
2N4265	Si-NPN	=2N4264:B>100	7e	-	BSS10..11,BSX19..20,2N2368..69(A),..
2N4266	Si-NPN	=2N4264:B=40..400	7e	-	BSS10..11,BSX19..20,2N2368..69(A),..
2N4267	MOS-P-FET-e	Sw,30V,Idss<1nA,Up<6V	5n+	Fch,Isi,Tdy	3N163
2N4268	MOS-P-FET-e	Sw,30V,Idss<1nA,Up<6V	5n+	Fch,Isi,Tdy	-
2N4269	Si-NPN	Nix,200V,0,03A,0,36W	2a$	Csr,Sem,Tra	BF298..299,BF422,2SC3467
2N427	Ge-PNP	30V,0.4A,0.15W,B>40,11MHz	2a	USA,Tix	ASY76..77
2N4270	Si-NPN	=2N4269:0,2W	2a	-	BF258..259,BF658..659,2N5058..59..
2N4271	Si-NPN	Sw,175V,1A,5W(Tc=100°),>20MHz	2a$	USA	BSS48..49,BUX50..52,2N3439..40..
2N4272	Si-NPN	Sw,175V,2,5A,5W(Tc=100°),>10MHz	2a$	USA	BUX50..52,2SC1861..62,2SD625
2N4273	Si-NPN	Sw,Pow,175V,2,5A,25W,>10MHz	22a$	USA	BD241F,BUX67,2SD386(A),2SD1138..
2N4274	Si-NPN	Fast-Sw,30V,0,1A,0,2W,>400MHz,<12/12nS	8a	USA,Nsc,Sgs	BSV91..92,BSX92..93,2N2368..69(A),..
2N4275	Si-NPN	=2N4274:40V	8a	-	BSV91..92,BSX92..93,2N2368..69(A),..
2N4276	Ge-PNP	AF,Sw-Pow,30V,60A,170W,B>60	23a$	Gpd,Mot	2N5435..40
2N4277	Ge-PNP	=2N4276:B>120	23a$	-	2N5435..40
2N4278	Ge-PNP	=2N4276:45V	23a$	-	2N5435..40
2N4279	Ge-PNP	=2N4276:45V,B>120	23a$	-	2N5435..40
2N428	Ge-PNP	30V,0.4A,0.15W,B>60,17MHz	2a	USA,Tix	ASY76..77
2N4280	Ge-PNP	=2N4276:60V	23a$	-	2N5435..40
2N4281	Ge-PNP	=2N4276:60V,B>120	23a$	-	2N5435..40
2N4282	Ge-PNP	=2N4276:75V	23a$	-	2N5435..40
2N4283	Ge-PNP	=2N4276:75V,B>120	23a$	-	2N5435..40
2N4284	Si-PNP	AF,Sym,25/25/25V,0,05A,0,25W	10b	Nsc,Pih	-
2N4285	Si-PNP	=2N4284:35/35/35V	10b	-	-
2N4286	Si-NPN	AF,30V,0,05A,0,25W	10b	Nsc,Pih	BC168,BC183,BC238,BC548..
2N4287	Si-NPN	45V,0.1A,0.25W,40MHz	10b	-	BC167,BC182,BC237,BC547..
2N4288	Si-PNP	AF,LN,30V,0,05A,0,25W,150MHz	10b	Nsc,Pih	BC214,BC259,BC309,BC559..
2N4289	Si-PNP	=2N4288:60V	10b	-	2SA872(A),2SA970,2SA1049,2SA1137..
2N428A	Ge-PNP	=2N425:B>80	2a	-	ASY76..77
2N429	Si-NPN	-		Gen	-
2N4290	Si-PNP	AF,LN,30V,0,2A,0,25W,150MHz	10b	Mic,Nsc,Pih	BC214,BC259,BC309,BC559..

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2N4291	Si-PNP	40V,0.2A,0.25W,150MHz	10b	-	BC415..416,BC560,2SA872(A),2SA970..
2N4292	Si-NPN	VHF/IF,30V,0,06A,0,2W,730MHz	10b	Mic,Nsc,Pih	BF225,BF314,BFS02,BFS05,BF507..
2N4293	Si-NPN	VHF/IF,30V,0,06A,0,2W,730MHz	10b	Mic,Nsc,Pih	BF225,BF314,BFS02,BFS05,BF507..
2N4294	Si-NPN	Sw,30V,0,2A,0,2W,<21/30nS	10b	Mic,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N4295	Si-NPN	Sw,40V,0,2A,0,2W,<24/30nS	10b	Mic,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N4296	Si-NPN	Sw,Pow,350/250V,1A,20W,>20MHz,B>50	22a$	USA,Rca	BUW40(A,B),TIP47..50,2N4240..
2N4297	Si-NPN	=2N4296:B>75	22a$	-	BUW40(A,B),TIP47..50,2N4240..
2N4298	Si-NPN	=2N4296:500/350V,B>25	22a$	-	BUW40A,B,BUX84,TIP50,2N4240..
2N4299	Si-NPN	=2N4296:500/350V,B>50	22a$	-	BUW40A,B,BUX84,TIP50,2N4240..
2N43(A)	Ge-PNP	AF/HF,45V,0,3A,0,15W,1,3MHz	1a&	USA	ASY48,ASY76..77,2N1189..1190
2N430	Si-NPN	-		Gen	-
2N4300	Si-NPN	AF,Sw-Pow,100V,2A,15W(Tc=100°),>30MHz	2a$	USA,Tix	BUX49,BUY41,2N5339,2SC1860
2N4301	Si-NPN	Sw,Pow,100/80V,10A,50W(Tc=100°),>40MHz	49a$	USA,Tix	2N5288..89,2N5339,2N5542
2N4302	N-FET	GenP,LN,30V,0.3W,Idss>0,5mA,Up<4V	8b	USA,Mic,Nsc	BFS70,2N3821,2N4220,2SK104,2SK301
2N4303	N-FET	GenP,LN,30V,Idss>4mA,Up<6V	8b	USA,Mic,Nsc	BFS80,BFW11,2N4416,2N5362,2N5245
2N4304	N-FET	GenP,LN,30V,Idss>0,5mA,Up<10V	8b	USA,Mic,Nsc	2N3365
2N4305	Si-NPN	AF,Sw,120V,5A,1,5W,<140/400nS,B>50	2a$	USA,Tix	BFT34,BUX34,BUY80,2N4895..97,2N5339
2N4306	Si-NPN	=2N4305:30W	?5S	-	-
2N4307	Si-NPN	=2N4305:100V	2a$	-	BFT33,BUX34,BUY80,2N4895..97,2N5339
2N4308	Si-NPN	=2N4307:30W	?5S	-	-
2N4309	Si-NPN	=2N4305:B>40	2a$	-	BFT34,BUX34,BUY80,2N4895..97,2N5339
2N431	Si-NPN	-		Gen	-
2N4310	Si-NPN	=2N4309:30W	?5S	-	-
2N4311	Si-NPN	=2N4305:100V,B>40	2a$	-	BFT33,BUX34,BUY80,2N4895..97,2N5339
2N4312	Si-NPN	=2N4311:30W	?5S	-	-
2N4313	Si-PNP	Sw,12V,0,1A,0,2W,<25/35nS	8a	USA,Mic,Nsc	BSX36
2N4314	Si-PNP	AF,Sw,90V,1A,1W,>60MHz	2a$	USA,Nsc,Rca	BCX60,BSS17,BSS44,BSV17,2N3634..37
2N4315	Si-NPN	Dual,30V,0,05A,0,4W,>100MHz	81bs	Amp	2N3409..11
2N4316	Thy-50Hz	100V,8A(Tc=85°),Igt/Ih<15/<25mA	22a$	Fch,Ssi	BStC0506,TAG671-100,TAG676-100
2N4317	Thy-50Hz	=2N4316:200V	22a$	-	BStC0513,TAG671-200,TAG676-200
2N4318	Thy-50Hz	=2N4316:300V	22a$	-	BStC0526,TAG671-300,TAG676-300
2N4319	Thy-50Hz	=2N4316:400V	22a$	-	BStC0526,TAG671-400,TAG676-400
2N432	Si-NPN	30V,0,1A,0,15W,>10MHz	2a	Gen	-
2N4320	Thy-GTO	30V,0,25A(Tc=75°),Igt/Ih<0,5/<3mA	2	Sem,Sld	-
2N4321	Thy-GTO	=2N4320:60V	2	-	-
2N4322	Thy-GTO	=2N4320:100V	2	-	-
2N4323	Thy-GTO	=2N4320:150V	2	-	-
2N4324	Thy-GTO	=2N4320:200V	2	-	-
2N4325	Thy-GTO	=2N4320:250V	2	-	-
2N4326	Thy-GTO	30V,0,39A(Tc=75°),Igt/Ih<0,5/<3mA	2	Sem,Sld	-
2N4327	Thy-GTO	=2N4326:60V	2	-	-
2N4328	Thy-GTO	=2N4326:100V	2	-	-
2N4329	Thy-GTO	=2N4326:150V	2	-	-
2N433	Si-NPN	30V,0,1A,0,15W,>10MHz	2a	Gen	-
2N4330	Thy-GTO	=2N4326:200V	2	-	-
2N4331	Thy-GTO	=2N4326:250V	2	-	-
2N4338	N-FET	GenP,LN,50V,Idss>0,2mA,Up<1V	2b&	USA,EUR	BFW13
2N4339	N-FET	GenP,LN,50V,Idss>0,5mA,Up<1,8V	2b&	USA,EUR	2N5358,2SK83,2SK193,2SK195,2SK238
2N434	Si-NPN	-		Gen	-
2N4340	N-FET	GenP,LN,50V,Idss>1,2mA,Up<3V	2b&	USA,EUR	BFW12,2N5484
2N4341	N-FET	GenP,LN,50V,Idss>3mA,Up<6V	2b&	USA,EUR	BF256,BFS71,3N3822,2N4221,2N5361..
2N4342	P-FET	GenP,LN,25V,Idss>4mA,Up<5,5V	8b	USA,Mot,Nsc	2N5116
2N4343	P-FET	GenP,LN,25V,Idss>10mA,Up<10	8b	Fch,Isi	BFT11
2N4346	Ge-PNP	TV-HD,320/60V,10A,5W(Tc=80°)	23a$	Gpd,Rca,Stc	AU106,AU109,AU111..112,2N5325
2N4347	Si-NPN	AF,Sw-Pow,140V,5A,100W,>0,2MHz	23a$	USA,EUR	BDX12,2N5760,2SD732..733,2SD551..
2N4348	Si-NPN	AF,Sw-Pow,140V,10A,120W,>0,2MHz	23a$	USA,EUR	BDX51,2N5634,2SD732..733,2SD551..
2N4349	Si-NPN	AF,Sw,65V,2A,7W(Tc=25°),<55/165nS	2a$	Sca,Ssi,Tra	BSS14,2N5262
2N4350	Si-NPN	AF,Sw,65V,0,35A,7W(Tc=25°),>300MHz	2a$	Sem,Sca,Ssi	BSS27,BSV95,2N3722..23,2SC1386..
2N4351	MOS-N-FET-e	Sw,30V,30mA,0.3W,140KHz,Idss<10nA,Up<5V	5g+	Gie,Isi,Mot	-
2N4352	MOS-P-FET-e	Sw,30V,Idss<10nA,Up<5V	5g+	Gie,Mot	-
2N4353	MOS-P-FET-e	Sw,30V,Idss<5nA,Up<5V	5n+	Gie,Isi	-
2N4354	Si-PNP	AF,Sw,60V,0,5A,0,35W,<100/400nS	8a	USA,Nsc,Sgs	BC327A,BC638,BSW24,2N2906..07(A)..
2N4355	Si-PNP	AF,Sw,60V,0,5A,0,35W,<100/400nS	8a	-	BC327A,BC638,BSW24,2N2906..07(A)..
2N4356	Si-PNP	AF,Sw,80V,0,5A,0,35W,<100/400nS	8a	-	BC640,BCX39,2SB647,2N4029

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2N4357	Si-PNP	Vid,240V,0,05A,0,4W,>40MHz	2a$	Fch,Sca,Sgs	BF436..437,BF492..493,2SA1371..
2N4358	Si-PNP	=2N4357:0,7W	2a$	-	BFQ36..37,BFT44..45,2SB606..
2N4359	Si-PNP	GenP,45V,0,05A,0,36W,>20MHz	2a$	USA,Sgs	BC212,BC257,BC307,BC557..
2N4360	P-FET	GenP,LN,20V,Idss>3mA,Up<10V	8b,7c	USA,Mic,Mot	-
2N4361(A)	Ge-NPN	AF,Sw,30V,0,4A,0,1(A:0,15)W,>2,5MHz	2a&	USA,Tix	ASY73..75
2N4381	P-FET	GenP,LN,25V,Idss>3mA,Up<5V	2a&	Fch,Nsc,Sol	2N5461,2N5464
2N4382	P-FET	GenP,LN,25V,Idss>10mA,Up<9V	2a&	Fch,Nsc,Sol	BFT11,2N4343
2N4383	Si-NPN	GenP,LN,40V,0,8A,0,8W,>120MHz	2a$	USA,Nsc	(BC140..141,BC300..302,2N3053,..)
2N4384	Si-NPN	=2N4383:0,5W	2a$	-	(BC337,BC635,BC637,BC639,..)
2N4385	Si-NPN	GenP,LN,40V,0,8A,0,8W,>120MHz	2a$	-	(BC140..141,BC300..302,2N3053,..)
2N4386	Si-NPN	=2N4385:0,5W	2a$	-	(BC337,BC635,BC637,BC639,..)
2N4387	Si-PNP	AF-Pow,40V,2A,20W	22a$	USA,Tix	BD240,BD242,BD934,2N3740..41..
2N4388	Si-PNP	=2N4387:60V	22a$	-	BD240A,BD242A,BD936,2N3740..41..
2N4389	Si-PNP	Sw,12V,0,1A,0,2W,<25/105nS	8a	Csr,Fch,Sgs	BSX36,2N4313
2N4439(A)	Ge-NPN	AF,Sw,30V,0,4A,0,1(A:0,15)W,>5MHz	2a&	USA,Tix	ASY73..75
2N4390	Si-NPN	Nix,120V,0,5W,>50MHz	2a	Sca,Sgs	BF297..299,BSS38,BSX21,2SC3467..
2N4391	N-FET	Sw,Chopper,40V,50mA,30Ω,Idss>50mA,Up<10V	2b&	USA,EUR	BFS74,BFS77,BSV78,2N3970,2N4859..
2N4392	N-FET	Sw,Chopper,40V,25mA,60Ω,Idss>25mA,Up<5V	2b&	USA,EUR	2N3971,2N5434
2N4393	N-FET	Sw,Chopper,40V,5mA,100Ω,Idss>5mA,Up<3V	2b&	USA,EUR	2N3972
2N4395	Si-NPN	AF,Sw-Pow,60V,5A,62W,>4MHz	23a$	USA	BD245A,BDV91,BDX91,2N4914..15..
2N4396	Si-NPN	=2N4395:80V	23a$	-	BD245B,BDV93,BDX93,2N5758..60..
2N4397	Si-NPN	VHF,AGC,40V,0,2W,>600MHz	5k	Sty	BF314,BFS02,BFS05,BFS07,BF562..
2N4398	Si-PNP	AF,Sw-Pow,40V,30A,200W,>4MHz	23a$	USA,Mot,Sgs	MJ4502
2N4399	Si-PNP	=2N4398:60V	23a$	-	2N5884,MJ4502
2N44(A)	Ge-PNP	AF/HF,45V,0,3A,0,15W,1MHz	1a&	USA	ASY48,ASY76..77,2N1189..1190
2N440(A)	Ge-NPN	AF,Sw,30V,0,4A,0,1(A:0,15)W,>10MHz	2a&	USA,Tix	ASY73..75
2N4400	Si-NPN	GenP,60V,0,6A,0,625W,<35/255nS,B>50	7e	USA,Gen,Mot	BC337A,BC637,BC639,2N2221..22(A)..
2N4401	Si-NPN	60V,0.6A,200MHz,B>100	7e	-	BC337A,BC637,BC639,2N2221..22(A)..
2N4402	Si-PNP	GenP,40V,0,6A,0,625W,<35/255ns,B>50	7e	USA,Gen,Mot	BC327,BC638,BC640,2N2906..07(A),..
2N4403	Si-PNP	40V,0.6A,200MHzB>100	7e	-	BC327,BC638,BC640,2N2906..09(A),..
2N4404	Si-PNP	AF,Sw,80V,1A,1,25W,<40/210nS,B>40	2a$	USA,Mot	BSV82,BSW40,2N4031,2N4033,2N4036
2N4405	Si-PNP	=2N4404:B>100	2a$	-	BSV82,BSW40,2N4031,2N4033,2N4036
2N4406	Si-PNP	AF,Sw,80V,2A,1,25W,<75/225nS,B>25	2a$	-	BSV82,2N6303
2N4407	Si-PNP	=2N4406:B>75	2a$	-	BSV82,2N6303
2N4409	Si-NPN	Nix,80V,0,25A,0,625W,>60MHz	7e	USA,Mot,Tix	BF391,BFP22,MPSA43,2SC1670..
2N441	Ge-PNP	AF,Sw-Pow,40V,Ueb=20V,15A,150W	38a$	USA,Mot	2N1980..82,2N2077..78,2N2491..
2N4410	Si-NPN	=2N4409:120V	7e	-	BF391,BFP22,MPSA43,2SC1670..
2N4411	Si-PNP	HF,15V,0,025A,0,15W,>400MHz	5g	Idi	BF324,BF414,BF506,BF709,BF914..
2N4412	Si-PNP	AF,40V,0,6A,0,6W,>20MHz,B>100	2a$	Sem,Spr	BC160..161,BC303..304,2N2904..05..
2N4412A	Si-PNP	=2N4412:60V	2a$	-	BC161,BC303..304,2N2904..05A..
2N4413(A)	Si-PNP	=2N4412(A):0,4W	2a$	-	BC327A,BC638,BC640,2N2906..07A..
2N4414	Si-PNP	=2N4412:B>40	2a$	-	BC160..161,BC303..304,2N2904..05..
2N4414A	Si-PNP	=2N4412:60V,B>40	2a$	-	BC161,BC303..304,2N2904..05A..
2N4415(A)	Si-PNP	=2N4414(A):0,4W	2a$	-	BC327A,BC638,BC640,2N2906..07A..
2N4416	N-FET	VHF/UHF,LN,30V,15mA,Idss>5mA,Up<6V	5h+	USA,EUR	BF256,BFS80,BFW11,2N5245,2N5398
2N4416A	N-FET	=2N4416:35V	5h+	-	BF256,BFS80,BFW11,2N5245,2N5398
2N4417(A)	N-FET	=2N4416(A):	24e	Mic,Sol,Uca	BF256,BFS80,BFW11,2N5245,2N5398
2N4418	Si-NPN	Sw,40V,0,2A,0,36W,>500MHz,<22/26nS	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),..
2N4419	Si-NPN	Sw,30V,0,2A,0,36W,>400MHz,<24/30nS	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),..
2N442	Ge-PNP	=2N441:50V,Ueb=30V	38a$	USA,Mot	2N1980..82,2N2077,2N2081,2N2491..
2N4420	Si-NPN	Sw,40V,0,2A,0,36W,>350MHz,<13/25nS	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),..
2N4421	Si-NPN	Sw,30V,0,2A,0,36W,>300MHz,<22/30nS	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),..
2N4422	Si-NPN	Sw,40V,0,2A,0,36W,>350MHz,<25/35nS	7a	Itt,Spe	BSS10..11,BSX19..20,2N2368..69(A),..
2N4423	Si-PNP	Sw,12V,0,2A,0,36W,>400MHz,<45/55nS	8a	Gen,Nsc,Tix	BSX36,2N4313
2N4424	Si-NPN	AF,Sw,60V,0,5A,0,36W	7c	USA,Gen,Tho	BC337A,BC637,BC640,2SD667..
2N4425	Si-NPN	=2N4424:0,56W	7co	-	BC337A,BC637,BC640,2SD667..
2N4427	Si-NPN	VHF-Dr/Out,40V,0,4A,1W,Pq=0,4W(400MHz)	2a$	USA,EUR	BFR98,BFS50,MRF515,MRF629,2N3948
2N4428	Si-NPN	UHF-Dr/Out,55V,0,4A,Pq=0,75W(500MHz)	2a$	USA,Mot,Tho	BFR97,2N3866
2N4429	Si-NPN	UHF-Dr/Out,55V,0,425A,Pq>1W(1GHz)	55r	USA,Tho,Tix	BLX91
2N443	Ge-PNP	=2N441:60V,Ueb=40V	38a$	USA,Mot	2N1981..82,2N2075..76,2N2491..
2N4430	Si-NPN	UHF-Pow,55V,1A,Pq>2,5W(1GHz)	55r	USA,Tho,Tix	BLW98,BLX98
2N4431	Si-NPN	UHF-Pow,55V,2A,Pq>5W(1GHz)	55r	USA,Tho,Tix	2SC3141
2N4432(A)	Si-NPN	GenP,50V,0,2A,0,6W,250MHz	2a$	Tho,Tix	BC140..141,BC300..302,2N2218..19..
2N4433	Si-NPN	HF,50V,0,03A,0,145W,200MHz	5k	Phi,Sty	BF240..241,BF254..255,BFS94..595,..

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2N4434	Si-NPN	HF,30V,0,03A,0,145W,300MHz	5k	Phi,Sty	BF240..241,BF254..255,BF594..595,..
2N4435	Si-NPN	HF,30V,0,03A,0,145W,220MHz	5k	Phi,Sty	BF240..241,BF254..255,BF594..595,..
2N4436	Si-NPN	GenP,60V,0,5A,0,2W,<60/150nS,B>40	8a	Fch,Sgs	BC337A,BC637,BSV59,2N2221..22(A)..
2N4437	Si-NPN	=2N4436:B>100	8a	-	BC337A,BC637,BSV59,2N2221..22(A)..
2N4438	Si-NPN	Vid,300V,0,2A,1W,>30MHz,B>40	2a$	Sca,Ssi,Sty	BF259,BF659,BFR59,BFS89,2N5058
2N4439	Si-NPN	=2N4438:B>100	2a$	-	BF259,BF659,BFR59,BFS89,2N5058
2N444	Ge-NPN	AF,Sw,15V,0,025mA,0,1W,>0,5MHz	2a&	USA	ASY28..29,ASY73..75
2N4440	Si-NPN	VHF/UHF-Pow,65V,1,5A,Pq>5W(400MHz)	49a	USA,Rca,Mot	-
2N4441	Thy-50Hz	50V,5,1A(Tc=73°),Igt/Ih<30/<40mA	16h$	Mot	-
2N4442	Thy-50Hz	=2N4441:200V	16h$	-	-
2N4443	Thy-50Hz	=2N4441:400V	16h$	-	-
2N4444	Thy-50Hz	=2N4441:600V	16h$	-	-
2N4445	N-FET	Sw,Chopper,25V,0,4A,Up<10V	2b&	Tix,Tdy	2N5432
2N4445A	N-FET	=2N4445:35V	2b&	-	-
2N4446	N-FET	Sw,Chopper,25V,0,4A,Up<5V	2b&	Tix,Tdy	2N5433
2N4446A	N-FET	=2N4446:35V	2b&	-	-
2N4447	N-FET	Sw,Chopper,20V,0,4A,Up<5V	2b&	Tix,Tdy	2N5432
2N4447A	N-FET	=2N4447:25V	2b&	-	-
2N4448	N-FET	Sw,Chopper,20V,0,4A,Up<5V	2b&	Tix,Tdy	2N5432
2N4448A	N-FET	=2N4448:25V	2b&	-	-
2N4449	Si-NPN	Sw,-/15V,0,2A,0,3W,<69/20nS	2a$	Fch,Ray,Sca	BSS11..12,BSX19..20,2N2368..69(A),..
2N444A	Ge-NPN	=2N444:40V,0,15W	2a&	-	-
2N445	Ge-NPN	AF,Sw,15V,0,05A,0,1W,>2MHz	2a&	USA	ASY28..29,ASY73..75
2N4450	Si-NPN	GenP,60V,0,5A,0,36W,50/125nS	2a$	Fch,Mot,Sgs	BC337A,BC637,BSV59,2N2221..22(A)..
2N4451	Si-PNP	Sw,-/12V,0,1A,0,3W,<65/95nS	2a$	Fch,Sgs	BSX36,2N4313,2N3209,2N4125..26..
2N4452	Si-PNP	Sw,45V,0,6A,0,35W,<95/210nS	2a	Fch,Sca,Sgs	BC327,BC638,BSW24,2N2906..07(A),..
2N4453	Si-PNP	GenP,25V,0,2A,0,3W,30/60nS	2a	Fch,Mot,Sgs	BC308,BC558,BSW24,2N3250..51(A),..
2N445A	Ge-NPN	=2N445:30V,0,15W	2a&	-	ASY28,ASY73..75
2N446	Ge-NPN	AF,Sw,15V,0,025A,0,1W,>5MHz	2a&	USA	ASY28..29,ASY73..75
2N446A	Ge-NPN	=2N446:30V,0,05A,0,15W	2a&	-	ASY28,ASY73..75
2N447	Ge-NPN	AF,Sw,15V,0,05A,0,1A,>9MHz	2a&	USA	ASY28..29,ASY73..75
2N447A	Ge-NPN	=2N447:30V,0,15W	2a&	-	ASY28,ASY73..75
2N447B	Ge-NPN	=2N447:25V,0,15W	2a&	-	ASY28..29,ASY73..75
2N448	Ge-NPN	HF,15V,0,02A,0,065W,5MHz	?1a	USA	-
2N449	Ge-NPN	HF,-/15V,0,02A,0,065W,8MHz	?1a	USA	-
2N45(A)	Ge-PNP	AF/HF,45V,0,01A,0,15W,1MHz	1a&	USA	ASY48,2SB56A
2N450	Ge-PNP	AF,Sw,20V,0,125A,0,15W,10MHz	1a	USA	ASY26..27,ASY76..77
2N451	Si-NPN	AF,Sw-Pow,65V,5A,85W,0,4MHz	-	Gen	(BD245A,BDV93,2SD895..896,..)
2N452	Si-NPN	AF,Sw-Pow,65V,5A,85W,0,4MHz,0,4MHz	-	Gen	(BD245A,BDV93,2SD895..896,..)
2N453	Si-NPN	AF,Sw-Pow,30V,2A,85W,0,4MHz	-	Gen	(BD245,BDV93,2SD895..896,..)
2N454	Si-NPN	AF,Sw-Pow,65V,2A,85W,0,4MHz	-	Gen	(BD245A,BDV93,2SD895..896,..)
2N456	Ge-PNP	Sw,Pow,40V,Ueb=20V,5A,50W,0,43MHz	23a$	USA,Mot,Tix	AL102..103,AUY21..22,2N1529..48..
2N456A,B	Ge-PNP	=2N456:7A,A:85W,B:150W	23a$	-	2N2288..93,2N3611..18
2N457	Ge-PNP	Sw,Pow,60V,Ueb=20V,5A,50W,0,43MHz	23a$	USA,Mot,Tix	AL102..103,AUY21..22,2N1545..48..
2N4576	Si-NPN	Sw,Pow,100V,150W	-	-	-
2N457A,B	Ge-PNP	=2N457:7A,A:85W,B:150W	23a$	-	2N2292..93,2N3615..18
2N458	Ge-PNP	Sw,Pow,80V,Ueb=20V,5A,50W,0,43MHz	23a$	USA,Mot,Tix	AL102..103,AUY21..22,2N1546..48..
2N458A,B	Ge-PNP	=2N458:7A,A:85W,B:150W	23a$	-	2N2292..93,2N3615..18
2N459(A)	Ge-PNP	AF,Sw-Pow,105V,5A,106W	23a$	USA,Mot	2N1537..38,2N1547..48,2N3616,2N3618
2N46	Ge-PNP	AF/HF,25V,Ueb=15V,0,015A,0,05W	-	Rca	AC125..126,AC151,ASY26..27
2N460	Ge-PNP	AF,Sw,45V,0,4A,0,225W,1,2MHz	2a&	USA,Mot	2N1189..90,2SB405ST
2N461	Ge-PNP	AF,Sw,45V,0,4A,0,225W,4MHz	2a&	USA,Mot	2N1189..90,2SB405ST
2N462	Ge-PNP	AF,Sw,40V,Ueb=40V,0,2A,0,15W	37e	Etc,Phc	2N1191..94,2SB56A
2N463	Ge-PNP	AF,Sw-Pow,60V,Ueb=50V,5A,37W,-/5,5µS	-	Wes	(2N1981..82,2N2075..76,2N2490..93,..)
2N464	Ge-PNP	AF,45V,Ueb=12V,0,5A,0,2W,0,7MHz	2a	USA,Mot	2N1189..90,2SB405ST
2N465	Ge-PNP	AF,45V,Ueb=12V,0,5A,0,2W,0,8MHz	2a	USA,Mot	2N1189..90,2SB405ST
2N466	Ge-PNP	AF,35V,Ueb=12V,0,5A,0,2W,1MHz	2a	USA,Mot	AC128,AC153,2N1189..90,2SB405ST
2N467	Ge-PNP	AF,35V,Ueb=12V,0,5A,0,2W,1,2MHz	2a	USA,Mot	AC128,AC153,2N1189..90,2SB405ST
2N468	Ge-NPN	AF,Sw-Pow,60V,Ueb=15V,3A,0,15MHz	-	Cbs,Gen	-
2N469(A)	Opto	-	-	-	-
2N47	Ge-PNP	AF,35V,0,02A,0,05W,0,8MHz	37d	Phc	AC125..126,AC151,ASY26..27
2N470(A)	Si-NPN	GenP,15V,0,025A,0,2W,>8MHz	2a	USA	BC168,BC183,BC238,BC548..
2N471(A)	Si-NPN	=2N470:30V	2a	USA	BC168,BC183,BC238,BC548..
2N472(A)	Si-NPN	=2N470:45V	2a	USA	BC167,BC182,BC237,BC547..

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2N473(A)	Si-NPN	GenP,15V,0,025A,0,2W,>8MHz	2a	USA	BC168,BC183,BC238,BC548..
2N474(A)	Si-NPN	=2N473:30V	2a	USA	BC168,BC183,BC238,BC548..
2N475(A)	Si-NPN	=2N473:45V	2a	USA	BC167,BC182,BC237,BC547..
2N476(A)	Si-NPN	GenP,15V,0,025A,0,2W,>12MHz	2a	USA	BC168,BC183,BC238,BC548..
2N477(A)	Si-NPN	=2N476:30V	2a	USA	BC168,BC183,BC238,BC548..
2N478(A)	Si-NPN	GenP,15V,0,025A,0,2W,>20MHz	2a	USA	BC168,BC183,BC238,BC548..
2N479(A)	Si-NPN	=2N478:30V	2a	USA	BC168,BC183,BC238,BC548..
2N48	Ge-PNP	AF,35V,0,02A,0,05W,0,8MHz	37d	Phc	AC125..126,AC151,ASY26..27
2N480(A)	Si-NPN	=2N478:45V	2a	USA	BC167,BC182,BC237,BC547..
2N481	Ge-PNP	HF,12V,0,02A,0,15W,3MHz	2a	USA	AF124..127,AF200
2N482	Ge-PNP	HF,12V,0,02A,0,15W,3,5MHz	2a	USA	AF124..127,AF200
2N483	Ge-PNP	HF,12V,0,02A,0,15W,5,5MHz	2a	USA	AF124..127,AF200
2N484	Ge-PNP	HF,12V,0,02A,0,15W,10MHz	2a	USA	AF124..127,AF200
2N485	Ge-PNP	HF,12V,0,01A,0,15W,7,5MHz	2a	USA	AF124..127,AF200
2N4851	UJT-P	Ip<2µA,Iv>2mA	5r$	Mot,Tix	2N4947,2N4948,2N4893
2N4852	UJT-P	=2N4851:Iv>4mA	5r$	-	2N4892
2N4853	UJT-P	=2N4851:Ip<0,4?A,Iv>6mA	5r$	-	-
2N4854	Si-P/N	NPN+PNP,60V,0,6A,0,6W,>200MHz,B>100	81bs	Mot,Sgs,Tix	BFX79
2N4855	Si-P/N	=2N4854:B>40	81bs	-	BFX79
2N4856(A)	N-FET	Sw,Sym,40V,Idss>50mA,Up<10V	2b&	USA,EUR	BFS74,BFS77,BSV78,2N3970,2N4391
2N4857(A)	N-FET	Sw,Sym,40V,Idss>20mA,Up<6V	2b&	USA,EUR	BFS75,BFS78,BSV79
2N4858(A)	N-FET	Sw,Sym,40V,Idss>8mA,Up<4V	2b&	USA,EUR	BFS76,BFS79,BSV80,2N4093
2N4859(A)	N-FET	Sw,Sym,30V,Idss>50mA,Up<10V	2b&	USA,EUR	BFS74,BFS77,BSV78,2N3970,2N4391
2N486	Ge-PNP	HF,12V,0,01A,0,15W,12MHz	2a	USA	AF124..127,AF200
2N4860(A)	N-FET	Sw,Sym,30V,Idss>20mA,Up<6V	2b&	USA,EUR	BFS75,BFS78,BSV79
2N4861(A)	N-FET	Sw,Sym,30V,Idss>8mA,Up<4V	2b&	USA,EUR	BFS76,BFS79,BSV80,2N4093
2N4862	Si-NPN	AF,Sw,140V,2A,4W(Tc=100°),>50MHz	2a	USA	(BUX49,BUY41,2SC1860)
2N4863	Si-NPN	AF,Sw,140V,2A,7W(Tc=25°),>50MHz	2a	USA	(BUX49,BUY41,2SC1860)
2N4864	Si-NPN	AF,Sw-Pow,140V,2A,29W,>50MHz	22a$	USA	2SC2529,2SC2660,2SD759..760
2N4865	Si-NPN	Sw,Pow,100/80V,90A,350W,>10MHz	49a$	USA	2N6309..11
2N4866	Si-NPN	=2N4865:140/120V	49a$	-	2N6309..11
2N4867(A)	N-FET	GenP,LN,40V,Idss>0,4mA,Up<2V	5h+	Isi,Tix,++	2N4339,2N5358,2SK83,2SK193,2SK195
2N4868(A)	N-FET	GenP,LN,40V,Idss>3mA,Up<3V	5h+	Isi,Tix,++	BC264,BF410,2SK192,2SK370
2N4869(A)	N-FET	GenP,LN,40V,Idss>2,5mA,Up<6V	5h+	Isi,Tix	BF256,BFS71,2N3822,2N4221..
2N487	Ge-PNP	HF,18V,0,025A,0,1W,>10MHz	2a	USA	AF124..127,AF200
2N4870	UJT-P	Ip<5µA,Iv>2mA	7o	Mot,Phi	2N4891
2N4871	UJT-P	=2N4870:Iv>4mA	7o	-	2N2646
2N4872	Si-PNP	Sw,RadH,12V,0,05A,0,3W,<25/30nS	2a$	Fch,Sgs	-
2N4873	Si-NPN	Sw,RadH,40V,0,2A,0,36W,<20/30nS	2a$	Fch,Sgs	-
2N4874	Si-NPN	VHF/UHF-Osc/Dr,30V,0,2A,0,72W,>900MHz	2a$	Ray,Sca,Tix	BFR36,2SC1199,2SC1252,2SC1365..66
2N4875	Si-NPN	VHF/UHF-Osc/Dr,40V,0,2A,0,72W,>800MHz	2a$	Ray,Sca,Tix	BFR36,2SC1199,2SC1252,2SC1365..66
2N4876	Si-NPN	VHF/UHF-Osc/Dr,40V,0,2A,0,72W,>650MHz	2a$	Ray,Sca,Tix	BFR36,2SC1199,2SC1252,2SC1365..66
2N4877	Si-NPN	AF,Sw,70V,4A,10W(Tc=25°),>30MHz	2a$	USA,Mot	BUX34,BUY80,2N5336..39
2N4878	Si-NPN	=2N4044:0,5W	81bs	Isi,Sol,Sty	→2N4044
2N4879	Si-NPN	=2N4100:0,5W	81bs	Isi,Sol,Sty	→2N4100
2N4880	Si-NPN	=2N4045:0,5W	81bs	Isi,Sol,Sty	→2N4045
2N4881	N-FET	Sw,300V,Idss>0,4mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5543
2N4882	N-FET	Sw,300V,Idss>1,5mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5543
2N4883	N-FET	Sw,200V,Idss>0,4mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5542..43
2N4884	N-FET	Sw,200V,Idss>1,5mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5542..43
2N4885	N-FET	Sw,125V,Idss>0,4mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5542..43
2N4886	N-FET	Sw,125V,Idss>1,5mA,Up<15V	2b&	Tdy,Tix,Tsc	2N5542..43
2N4888	Si-PNP	Vid,150V,0,05A,0,3W,>30MHz	8a	Fch,Spe	BF398,BF423,BF435..437,2SC1370..
2N4889	Si-PNP	=2N4888:>40MHz	8a	-	BF398,BF423,BF435..437,2SC1370..
2N489(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4890(S)	Si-PNP	AF,Sw,60V,0,5A,1W,35/130nS	2a$	USA,Mot	BC161,BC303..304,2N2904..05(A)..
2N4891(L)	UJT-P	Ip<5µA,Iv>2mA	7o	Mot,Tix	2N4870
2N4892(L)	UJT-P	=2N4891:Ip<2?A,Iv>4mA	7o	-	2N4852
2N4893(L)	UJT-P	=2N4891:Ip<2?A,Iv>2mA	7o	-	2N4851,2N4947,2N4948
2N4894(L)	UJT-P	=2N4891:Ip<1?A,Iv>2mA	7o	-	2N4949
2N4895	Si-NPN	Sw,120V,5A,1W,>50MHz,B>40	2a$	USA,Sgs	BFT34,BFX34,BUX34,BUY80
2N4896	Si-NPN	=2N4895:>80Mhz,B>100	2a$	-	BFT34,BUX34,BUY80
2N4897	Si-NPN	=2N4895:150V	2a$	-	BFX34,BUY80
2N4898	Si-PNP	AF,Sw-Pow,40V,1A,25W,>3MHz	22a$	USA,Fch,Mot	BD240,BD242,BDX14,2N3740..41..

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2N4899	Si-PNP	=2N4898:60V	22a$	-	BD240A,BD242A,BDX14,2N3740..41..
2N4898..494B	UJT-P	=2N489..494:Ip<6?A	5r,2p	-	-
2N489C..494C	UJT-P	=2N489..494:Ip<2?A	5r,2p	-	2N2647
2N49	Ge-PNP	AF,35V,0,02A,0,05W,0,8MHz	37d	Phc	AC125..126,AC151,ASY26..27
2N490(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4900	Si-PNP	=2N4898:80V	22a$	-	BD240B,BD242B,BDX14,2N3741..
2N4901	Si-PNP	AF,Sw-Pow,40V,5A,87,5W,>4MHz,B>20	23a$	USA,Fch,Mot.	BD246,BDV92,BDX92,MJ2955,2N5871..72..
2N4902	Si-PNP	=2N4901:60V	23a$	-	BD246A,BDV92,BDX92,MJ2955,2N5871..72..
2N4903	Si-PNP	=2N4901:80V	23a$	-	BD246B,BDV94,BDX94,MJ2955,2N5872..
2N4904	Si-PNP	=2N4901:B>25	23a$	-	BD246,BDV92,BDX92,MJ2955,2N5871..72..
2N4905	Si-PNP	=2N4901:60V,B>25	23a$	-	BD246A,BDV92,BDX92,MJ2955,2N5871..72..
2N4906	Si-PNP	80V,5A,87.5W,>4MHz,B>25	23a$	-	BD246B,BDV94,BDX94,MJ2955,2N5872..
2N4907	Si-PNP	AF,Sw-Pow,40V,10A(ss),150W,4MHz	23a$	USA,Sgs	BD312,BD546,BDW22,BDW52C,2N5875..76..
2N4908	Si-PNP	=2N4907:60V	23a$	-	BD312,BD546A,BDW22A,BDW52C,2N5875..76..
2N4909	Si-PNP	=2N4907:80V	23a$	-	BD314,BD546B,BDW22B,BDW52C,2N5876..
2N491(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4910	Si-NPN	AF,Sw-Pow,40V,1A,25W,>3MHz	22a$	USA,Fch,Mot	BD239,BD241,BDY78,2N4231..33..
2N4911	Si-NPN	=2N4910:60V	22a$	-	BD239A,BD241A,BDY78,2N4232..33..
2N4912	Si-NPN	=2N4910:80V	22a$	-	BD239B,BD241B,BDY78,2N4233..
2N4913	Si-NPN	AF,Sw-Pow,40V,5A,87,5W,>4MHz	23a$	USA,Fch,Mot	BD245,BDW51C,BDV91,BDX91,2N5873..74..
2N4914	Si-NPN	=2N4913:60V	23a$	-	BD245A,BDV91,BDW52C,BDX91,2N5873..74..
2N4915	Si-NPN	=2N4913:80V	23a$	-	BD245B,BDV93,BDW52C,BDX93,2N5874..
2N4916	Si-PNP	GenP,30V,0,1A,0,2W,>400MHz,<55/180nS	8a	Fch,Nsc,Sgs	BSW24,BSX36,2N2906..07(A),2N4125,..
2N4917	Si-PNP	=2N4916:>450MHz	8a	-	BSW24,BSX36,2N2906..07(A),2N4125,..
2N4918	Si-PNP	AF,Sw-Pow,Lo-sat,40V,1A,30W,>3MHz	14h$	Mot,Nsc,Sgs	BD136,BD166,BD176,BD234,BD238…
2N4919	Si-PNP	=2N4918:60V	14h$	-	BD138,BD168,BD178,BD236,BD238…
2N492(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4920	Si-PNP	80V,1A,30W	14h$	-	BD140,BD170,BD180,BD238,BD238…
2N4921	Si-NPN	AF,Sw-Pow,Lo-sat,40V,1A,30W,>3MHz	14h$	Mot,Nsc,Sgs	BD135,BD165,BD175,BD233,BD235…
2N4922	Si-NPN	=2N4921:60V	14h$	-	BD137,BD167,BD177,BD235..
2N4923	Si-NPN	80V,1A,30W	14h$	-	BD139,BD169,BD179,BD237..
2N4924(S)	Si-NPN	GenP,100V,0,2A,1W,>100MHz	2a$	USA,Mot,Nsc	BC141,BC300,2N1889..90,2N1893..
2N4925(S)	Si-NPN	=2N4924:150V	2a$	-	BSS48..49,2N3439..40,2N5010
2N4926	Si-NPN	Vid,200V,0,05A,1W,>30MHz	2a$	USA,Mot,Sgs	BF258..259,BF658..659,2N5058..59..
2N4927	Si-NPN	=2N4926:250V	2a$	-	BF258..259,BF658..659,2N5058..59..
2N4928(S)	Si-PNP	GenP,100V,0,1A,0,6W,>100MHz	2a$	USA,Mot	BFT44..45,2N3634..35,2SB606
2N4929(S)	Si-PNP	GenP,150V,0,5A,1W,>100MHz	2a$	USA,Mot	BFT44..45,2N3636..37,2SB606
2N493(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4930(S)	Si-PNP	GenP,200V,0,5A,1W,>20MHz	2a$	USA,Mot	BFT44..45,2N5415..16,2SB606
2N4931(S)	Si-PNP	GenP,250V,0,5A,1W,>20MHz	2a$	USA,Mot	BFT44..45,MJ5415..16,2N5416,2SB606
2N4932	Si-NPN	FM/VHF-Pow,50V,3,3A,Pq>12W(88MHz)	49a	Rca,Ssi,Tix	BLW36
2N4933	Si-NPN	FM/VHF-Pow,70V,3,3A,Pq>20W(88MHz)	49a	Rca,Ssi,Tix	2SC1037
2N4934	Si-NPN	VHF/UHF,50V,0,2W,>700MHz	5k	Mic,Nsc,Sca	BF377..378,BF689,BF763,2N2857..
2N4935	Si-NPN	VHF/UHF,50V,0,2W,>700MHz	5k	Mic,Nsc,Sca	BF377..378,BF689,BF763,2N2857..
2N4936	Si-NPN	VHF/UHF,50V,0,2W,>700MHz	5k	Mic,Nsc,Sca	BF377..378,BF689,BF763,2N2857..
2N4937	Si-PNP	Dual,50V,0,05A,0,6W,400MHz	81bs	Mot,Ray	2N3726..27,2N4015..16
2N4938	Si-PNP	Dual,50V,0,05A,0,6W,400MHz	B1bs	-	2N3726..27,2N4015..16
2N4939	Si-PNP	Dual,50V,0,05A,0,6W,400MHz	81bs	-	2N3726..27,2N4015..16
2N494(A)	UJT-P	60V,70mA,Ip<12µA,Iv>8mA,Rbb<6,8kΩ	5r,2p	Gen,Ssc,Tix	-
2N4940	Si-PNP	=2N4937:0,35W	10-FLP/ch	-	-
2N4941	Si-PNP	=2N4938:0,35W	10-FLP/ch	-	-
2N4942	Si-PNP	=2N4938:0,35W	10-FLP/ch	-	-
2N4943	Si-NPN	AF,Sw,120V,1A,0,8W,>150MHz	2a$	USA,Mic,Nsc	BSS42..43,BSW67..68,BSX47,2N2102..
2N4944	Si-NPN	GenP,80/40V,0,5A,0,22W,>60MHz,B>40	8a	USA,Nsc,Sgs	BC639,BCX24,2N3700..01,2SD667..
2N4945	Si-NPN	=2N4944:80/60V	8a	-	BC639,BCX24,2N3700..01,2SD667..
2N4946	Si-NPN	=2N4944:B>100	8a	-	BC639,BCX24,2N3700..01,2SD667..
2N4947	UJT-P	Ip<2µA,Iv>2mA	2r$	Mot,Tix	2N4851,2N4948,2N4893
2N4948	UJT-P	=2N4947	2r$	-	2N4851,2N4947,2N4893
2N4949	UJT-P	=2N4947:Ip<1?A	2r$	-	2N4894
2N495	Si-PNP	HF/Sw,25V,0,05A,0,15W,>8MHz	2a	USA	BC213,BC258,BC308,BC558..
2N4950	Si-NPN	Sw,Pow,80/60V,70A,200W	49a$	USA	2N6309..11
2N4951	Si-NPN	GenP,60V,0,5A,0,36W,250MHz,B>60	7c	USA,Nsc,Tho	BC337A,BC637,BSV59,2N2221..22(A)..
2N4952	Si-NPN	=2N4951:B>100	7c	-	BC337A,BC637,BSV59,2N2221..22(A)..
2N4953	Si-NPN	=2N4951:B>200	7c	-	BC337A,BC637,BSV59,2N2221..22(A)..

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2N4954	Si-NPN	=2N4951: 40V	7c	-	BC337, BC635, BSV59, 2N2221..22(A)..
2N4955(/78)	Si-NPN	Dual, 30V, 0,03A, 0,45W, >60MHz	81bs	Isi,Fch,Sca	2N3409..11
2N4956(/78)	Si-NPN	Dual, 30V, 0,03A, 0,45W, >60MHz	81bs	-	2N3409..11
2N4957	Si-PNP	UHF, LN, 30V, 0,03A, 0,2W, 1600MHz	5g	Mot,Sca,Tho	BF439, BF516, BF606, BFR38, BFR99..
2N4958	Si-PNP	UHF, LN, 30V, 0,03A, 0,2W, 1500MHz	5g	Mot,Sca,Tho	BF439, BF516, BF606, BFR38, BFR99..
2N4959	Si-PNP	UHF, LN, 30V, 0,03A, 0,2W, 1500MHz	5g	Mot,Sca,Tho	BF439, BF516, BF606, BFR38, BFR99..
2N496	Si-PNP	HF/Sw, 10V, 0,05A, 0,15W, >7,2MHz	2a	USA	BC213, BC258, BC308, BC558..
2N4960	Si-NPN	GenP, 60V, 1A, 0,8W, >250MHz	2a$	Fch,Sca,Ssi	BC140..141, BSW65..68, BSX45..47..
2N4961	Si-NPN	=2N4960: 80V	2a$	-	BC140..141, BSW65..68, BSX45..47..
2N4962	SI-NPN	=2N4960: 0,5W	2a$	-	BC637, BS540..41, BSX33, 2SD774..
2N4963	Si-NPN	=2N4960: 80V, 0,5W	2a$	-	BC639, BSS59, BSX33, 2SD774..
2N4964	Si-PNP	GenP, 50V, 0,1A, 0,2W, >60MHz, B>30	8a	Fch,Mic,Nsc	BC212, BC257, BC307, BC557..
2N4965	Si-PNP	=2N4964: B>80	8a	-	BC212, BC257, BC307, BC557..
2N4966	Si-NPN	GenP, 50V, 0,03A, 0,2W, >40MHz, B>40	8a	Fch,Mic,Nsc	BC167, BC182, BC237, BC547..
2N4967	Si-NPN	=2N4966: B>100	8a	-	BC167, BC182, BC237, BC547..
2N4968	Si-NPN	=2N4966: 30V	8a	-	BC168, BC183, BC238, BC548..
2N4969	Si-NPN	GenP, 50V, 0,5A, 0,2W, >200MHz, B>40	8a	Fch,Mic,Nsc	BC337, BC637, BSV59, 2N2221..22(A),..
2N497(A)	Si-NPN	GenP, 60V, 0,5A, 0,8(A: 1)W, 50MHz	2a$	Fch,Tix,++	BC140..141, BC300..302, 2N3053..
2N4970	Si-NPN	=2N4969: B>100	8a	-	BC337, BC637, BSV59, 2N2221..22(A),..
2N4971	Si-PNP	GenP, 50V, 0,5A, 0,2W, >200MHz, B>40	8a	Fch,Mic,Nsc	BC327, BC638, BSW24, 2N2906..07(A),..
2N4972	Si-PNP	=2N4971: B>100	8a	-	BC327, BC638, BSW24, 2N2906..07(A),..
2N4973	SI-PNP	VHF/UHF, 20V, 0,03A, 0,2W, >800MHz	8a	Ray	BF316, BF439, BF516, BF606, BFR38..
2N4974	Si-PNP-Darl	GenP, 40V, 1A, 0,8W, a>25000	5r$	Mot,Ray	-
2N4975	Si-PNP-Darl	=2N4974: a>15000	5r$	-	-
2N4976	Si-NPN	UHF-Pow, 55V, 0,4A, 5W, >1GHz	55v	Trw	(BLW90, MRF5174)
2N4977	N-FET	Sw, Chopper, 30V, Idss>50mA, Up<10V	2b&	USA,Tho,Tix	BFS74, BFS77, BSV78, 2N3970, 2N4391..
2N4978	N-FET	Sw, Chopper, 30V, Idss>15mA, Up<8V	2b&	USA,Tho,Tix	BFS75, BFS78, BSV79, 2N4857, 2N4092..
2N4979	N-FET	Sw, Chopper, 30V, Idss>7,5mA, Up<5V	2b&	USA,Tho,Tix	BFS76, BFS79, BSV80, 2N4858, 2N4093..
2N498(A)	Si-NPN	=2N497: 100V	2a$	Fch,Tix,++	BC141, BC300, 2N1889..90, 2N1990..
2N4980	Si-PNP	Chopper, 30/30/30V, 0,1A, 0,4W	2a$	Tdy	2N2946
2N4981	Si-PNP	Chopper, 50/50/50V, 0,1A, 0,4W	2a$	Tdy	-
2N4982	Si-PNP	Chopper, 70/70/70V, 0,1A, 0,4W	2a$	Tdy	-
2N4983	SUS	Ub=6..10V, µS<0,5mA, Itsm=5A	2h&(AKG)	Gen	-
2N4984	SUS	Ub=7,5..9V, µS<0,15mA, Itsm=5A	2h&(AKG)	Gen	-
2N4985	SUS	Ub=7,5..8,2V, µS<0,3mA, Itsm=5A	2h&(AKG)	Gen	-
2N4986	SUS	Ub=7..9V, µS<0,2mA, Itsm=5A	2h&(AKG)	Gen	-
2N4987	SUS	=2N4983:	7g(KGA)	Gen	-
2N4988	SUS	=2N4984:	7g(KGA)	Gen	-
2N4989	SUS	=2N4985:	7g(KGA)	Gen	-
2N499(A)	Ge-PNP	VHF, 30V, 0,05A, >120MHz	2a	USA,Tix	AF106, AF109R, AF306
2N4990	SUS	=2N4986:	7g(KGA)	Gen	-
2N4991	SBS	Ub=6..10V, µS<0,5mA, Itsm=5A	7e(A2GA1)	Gen	-
2N4992	SBS	Ub=7,5..9V, µS<0,12mA, Itsm=5A	7e(A2GA1)	Gen	BS08A
2N4993	SBS	Ub=6..10V, µS<0,5mA, Itsm=5A	7e(A2GA1)	Gen	-
2N4994	Si-NPN	HF/AF, 60V, 0,3A, 0,36W, 300MHz, B>40	7a	Gen,Mic,Tix	BF240..241, BF254..255, BF594..595,..
2N4995	Si-NPN	=2N4994: B>100	7a	-	BF240..241, BF254..255, BF594..595,..
2N4996	Si-NPN	VHF, 30V, 0,05A, 0,25W, >600MHz, B>50	7a	Mic,Sca,Tix	BF314, BFS02, BFS05, BFS07, BFS62..
2N4997	Si-NPN	=2N4996: B>30	7a	-	BF314, BFS02, BFS05, BFS07, BFS62..
2N4998	SI-NPN	Sw, Pow, 100V, 2A, 30W, >50MHz, B>30	49a	USA,Tix	2N5002, 2N5004, 2N5284..85, 2N5339
2N4999	Si-PNP	Sw, Pow, 100V, 2A, 30W, >50MHz, B>30	49a	USA,Tix	2N5003, 2N5005, 2N5286..87
2N50	Ge-PNP	Sw, 15V, 1mA, 0,05W, 3MHz	-	Clv	(ASY26..27, ASY48)
2N500	Ge-PNP	VHF, 20V, 0,05W	2a	Sem	AF109R, AF139, AF239(S)
2N5000	Si-NPN	=2N4998: >60MHz, B>70	49a	-	2N5002, 2N5004, 2N5284..85, 2N5339
2N5001	Si-PNP	=2N4999: >60MHz, B>70	49a	-	2N5003, 2N5005, 2N5286..87
2N5002	SI-NPN	Sw, Pow, 100V, 5A, 50W(Tc=50°), B>30	49a	USA,Tix	2N5284..85, 2N5339
2N5003	Si-PNP	Sw, Pow, 100V, 5A, 50W(Tc=50°), B>30	49a	USA,Tix	2N5286..87
2N5004	Si-NPN	=2N5002: B>70	49a	-	2N5284..85, 2N5339
2N5005	Si-PNP	=2N5003: B>70	49a	-	2N5286..87
2N5006	Si-NPN	Sw, Pow, 100V, 10A, 67W(Tc=60°), B>30	49a	USA	2N5288..89
2N5007	Si-PNP	Sw, Pow, 100V, 10A, 67W(Tc=100°), B>30	49a	USA	2N5290..91
2N5008	Si-NPN	=2N5006: B>70	49a	-	2N5288..89
2N5009	Si-PNP	=2N5007: B>70	49a	-	2N5290..91
2N501(A)	Ge-PNP	Sw, 15V, 0,05A, 0,06W, 90MHz, <-/22nS	2a	USA	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N5010	Si-NPN	Sw, 500V, 0,5A, 4W(Tc=25°), 15MHz	2a$	Sca,Ssi,Stc	BUY59..60, 2N3439, 2N5059, 2SD793..794+

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2N5011	Si-NPN	=2N5010:600V	2a$	-	BUY60,2N5097..99,2SC1762,2SD594
2N501-18	Ge-PNP	Sw,15V,0,2A,0,15W,90MHz,<-/22nS	2a	USA	ASZ21,2N705(A),2N2635,2N2955..57
2N5012	Si-NPN	=2N5010:700V	2a$	-	2N5098..99,2SC1762,2SD594
2N5013	Si-NPN	=2N5010:800V	2a$	-	2N5099,2SD594
2N5014	Si-NPN	=2N5010:900V	2a$	-	-
2N5015	Si-NPN	=2N5010:1000V	2a$	-	-
2N5016	Si-NPN	UHF-Pow,65V,4,5A,Pq>15W(400MHz)	49a*	Mot,Rca,Sem	-
2N5017	Si-NPN	UHF-Pow,65V,4,5A,Pq>15W(400MHz)	-	Rca	-
2N5018	P-FET	GenP,30V,Idss>10mA,Up<10V	2a&	USA,Nsc,Tix	2N3993
2N5019	P-FET	GenP,30V,Idss>5mA,Up<5V	2a&	USA,Nsc,Tix	2N5116
2N502(A,B)	Ge-PNP	VHF,20V,0,05A,0,06W,220MHz,A,B:30V,0,075W	2a	USA,Mot	AF106,AF109R,AF306
2N5020	P-FET	GenP,25V,Idss>0,3mA,Up<1,5V	2a&	USA,Fch,Nsc	2N2844
2N5021	P-FET	GenP,25V,Idss>1mA,Up<2,5V	2a&	USA,Fch,Nsc	2SJ74
2N5022	Si-PNP	Sw,50V,0,5A,1W,<45/95ns	2a$	USA,Fch,Mic	2N3468,2SA717,2SA742
2N5023	Si-PNP	Sw,30V,0,5A,1W,<45/95nS	2a$	=2N5022	2N3467..68,2SA717,2SA742
2N5024	Si-NPN	UHF,20V,15mA,0,2W,>1300MHz	5g	Sca	BF377..378,BF630,BFR15,BFW99..
2N5025	Si-NPN	HF-Pow,75V,5A,Pq>20W(50MHz)	49a*	Fch,Tix	-
2N5026	Si-NPN	HF-Pow,90V,5A,Pq>25W(50MHz)	49a*	Fch,Tix	-
2N5027	Si-NPN	Sw,-/30V,0,35A,0,32W,<35/60nS	7c	Gen,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N5028	Si-NPN	Sw,-/30V,0,35A,0,32W,<45/70nS	7c	Gen,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N5029	Si-NPN	Sw,-/15V,0,2A,0,32W,<22/26nS	7c	Gen,Mic,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N503	Ge-PNP	VHF,20V,0,05A,0,025W,>168MHz	2a	USA	AF109R,AF139,AF239(S)
2N5030	Si-NPN	Sw,-/12V,0,2A,0,32W,<24/30nS	7c	Gen,Mic,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..
2N5031	Si-NPN	UHF,LN,15V,0,02A,0,2W,>1GHz	5g	USA,Mot	BF377..378,BF689,BF763,2N2857..
2N5032	Si-NPN	UHF,LN,15V,0,02A,0,2W,>1GHz	5g	USA,Mot	BF377..378,BF689,BF763,2N2857..
2N5033	P-FET	GenP,20V,Idss>0,3mA,Up<2,5V	8b	USA,Fch,Nsc	2N2607
2N5034	Si-NPN	AF,Sw-Pow,55V,6A,83W,>0,8MHz	-	Rca	BD245,BD545A,BDV91,2N3055,2SC3256..
2N5035	Si-NPN	AF,Sw-Pow,55V,6A,83W,>0,8MHz	-	Rca	BD245,BD545A,BDV91,2N3055,2SC3256..
2N5036	Si-NPN	=2N5034:70V,8A	-	Rca	BD245A,BD545B,BDV93,2N3055,2SC3256..
2N5037	Si-NPN	=2N5035:70V,8A	-	Rca	BD245A,BD545B,BDV93,2N3055,2SC3256..
2N5038	Si-NPN	150V,20A,140W,0.5µS	-		-
2N5038(-1)	Si-NPN	Sw,Pow,150/90V,20A,140W,>60MHz	23a$	Toshiba	BUV10,BUW57,BUX10,BUX40
2N5039(-1)	Si-NPN	=2N5038:120V	23a$	-	BUV10,BUW57,BUX10,BUX40
2N504	Ge-PNP	HF,35V,0,05A,0,03W,>50MHz	2a	USA	AF124..126,AF200
2N5040	Si-PNP	GenP,25V,1A,0,3W,>80MHz	2a	Fch	BC160..161,BC327..328,BC636..
2N5041	Si-PNP	GenP,40V,1A,0,3W,>100MHz	2a	Fch	BC160..161,BC327..328,BC636..
2N5042	Si-PNP	GenP,40V,1A,0,8W,>100MHz	2a$	Fch	BC160..161,BCX60,2N2904..05(A)..
2N5043	Ge-PNP	VHF/UHF,LN,15V,0,03A,>1500MHz	5g	Ssi,Tix	(AF239(S))
2N5044	Ge-PNP	VHF/UHF,LN,15V,0,03A,>1000MHz	5g	Ssi,Tix	(AF239(S))
2N5045	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	USA,Nsc,Tix	BFQ10..16,2N3921..22,2N3954..58
2N5046	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N3921..22,2N3954..58
2N5047	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N3921..22,2N3954..58
2N5048	Si-NPN	Sw,Pow,120V,10A,50W(Tc=100°),>10MHz	49a$	USA	2N5288..89,2N5542
2N5049	Si-NPN	=2N5048:60V	49a	USA	2N5288..89,2N5542
2N505	Ge-PNP	AF,40V,Ueb=40V,0,25A,0,125W,8MHz	2a	Csr,Etc	(ASY48,ASY76..77)
2N5050	Si-NPN	AF,Sw-Pow,125V,2A,40W,>10MHz	22a$	USA,Mot,Rca	BD241D,BUX67(A..C),2N3441,2SD1138..
2N5051	Si-NPN	=2N5050:150V	22a$	-	BD241D,BUX67(A..C),2N3441,2SD1138..
2N5052	Si-NPN	=2N5050:200V	22a$	-	BD241F,BUX67(A..C),2N3583,2SD1138..
2N5053	Si-NPN	UHF,30V,0,025A,0,2W,>1300MHz	5g	Amp,Sca,Ssi	BF377..378,BF630,BFR15,BFW99..
2N5054	Si-NPN	UHF,30V,0,025A,0,2W,>1500MHz	5g	Amp,Sca,Ssi	BF377..378,BF630,BFR15,BFW99..
2N5055	Si-PNP	Sw,12V,0,1A,0,2W,<25/35nS	8a	Fch,Nsc	BSX36,2N4313
2N5056	Si-PNP	Sw,15V,0,1A,0,36W,<25/45nS	2a$	Fch,Itt,Nsc	BSX36,2N4313
2N5057	Si-PNP	Sw,15V,0,1A,0,36W,<25/45nS	2a$	Fch,Itt,Nsc	BSX36,2N4313
2N5058(S)	Si-NPN	Sw,Vkd,300V,0,15A,1W,>30MHz	2a$	USA,Mot,Tix	BF259,BF659,BFS89,BFR59
2N5059(S)	Si-NPN	=2N5058:250V	2a$	-	BF258..259,BF658..659,BFS89..
2N506	Ge-PNP	AF,Sw,40V,0,1A,0,05W,>0,6MHz	?1a	Csr,Etc	2N1191..94,2SB56A
2N5060	Thy-50Hz	30V,0,51A(Tc=67°),Igt/Ih<0,2/<5mA	7e	Gen,Mot,Tag	2N6564,TIC60,MCR100-3,BRY55/30..
2N5061	Thy-50Hz	=2N5060:60V	7e	-	2N6564,TIC61,MCR100-3,BRY55/60..
2N5062	Thy-50Hz	=2N5060:100V	7e	-	2N6564,TIC62,MCR100-3,BRY55/100,..
2N5063	Thy-50Hz	=2N5060:150V	7e	-	2N6564,TIC63,MCR100-4,BRY55/200,..
2N5064	Thy-50Hz	=2N5060:200V	7e	-	2N6564,TIC64,MCR100-4,BRY55/200,..
2N5065	Si-NPN	Sw,RadH,25V,0,5A,0,6W,<19/40nS	2a$	Fch,Sca,Sgs	-
2N5066	Si-NPN	Chopper,30/20/30V,0,1A,0,4W	2a$	Tdy	-
2N5067	Si-NPN	AF,Sw-Pow,40V,5A,87,5W,>4MHz	23a$	USA,Mot,Tix	BD245,BDV91,BDX91,2N4914..15..

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2N5068	Si-NPN	=2N5067: 60V	23a$	-	BD245A, BDV91, BDW51C, BDX91, 2N4914..15..
2N5069	Si-NPN	=2N5057: 80V	23a$	-	BD245B, BDV93, BDW51C, BDX93, 2N5758..60..
2N507	Ge-NPN	AF, Sw, 40V, 0, 1A, 0,05W, >0,6MHz	71a	Csr,Etc	-
2N5070	Si-NPN	AM-Pow, 65V, 3,3A, Pep=25W(30MHz)	49a*	Mot,Rca,Sem	2N5026
2N5071	Si-NPN	FM-Pow, 65V, 3,3A, Pq>24W(76MHz)	49a*	-	2N5026
2N5072	Si-NPN	Sw, Pow, 100V, 10A, 125W, >40MHz	-	Ssi,Tho,Trw	-
2N5073	Si-NPN	Vid, 180V, 0,4A, 0,6W, >40MHz	2a$	Sca,Ssi,Tho	BFW36, BSS48, 2SD413, 2SD576, 2SD624
2N5074	Si-NPN	Sw, Pow, 200/200V, 3A, 40W(Tc=100°), B>30	49a	USA	-
2N5075	Si-NPN	=2N5074: B>90	49a	-	-
2N5076	Si-NPN	=2N5074: 250/250V	49a	-	-
2N5077	Si-NPN	=2N5074: 250/250V, B>90	49a	-	-
2N5078	N-FET	VHF/UHF, LN, 30V, Idss>4mA, Up<8V	5g+	USA,Isi,Nsc	BF244B..245B, BFS72, 2N3823, 2N5398
2N5079	Si-NPN	GenP, 60V, 1A, 0,36W, >400MHz	2a$	Csr,Idi,Tdy	BFX94..95, 2N3737, 2N4014
2N508	Ge-PNP	AF-Driver, 18V, 0,5A, 0,225W, 4,5MHz	2a&	USA,Mot	AC128, AC152..153, AC188
2N5080	Si-NPN	GenP, 60V, 1A, 0,36W, >500MHz	2a$	-	BFX94..95, 2N3737, 2N4014
2N5081	Si-NPN	HF, 70V, 0,36W, >600MHz	2a$	Csr,Idi,Tdy	-
2N5082	Si-NPN	HF, 60V, 0,36W, >600MHz	2a$	-	-
2N5083	Si-NPN	Sw, Pow, 120V, 10A, 25W(Tc=100°), B>40	49a	USA	2N5339
2N5084	Si-NPN	=2N5083: B>100	49a	-	(2N5288..89, 2N5542)
2N5085	Si-NPN	=2N5083: 150V	49a	-	2N5339
2N5086	Si-PNP	AF, LN, 50V, 0,05A, 0,625W, B>150	7e	USA,Fer,Mot	BC214, BC416, BC560, 2SA872(A)..
2N5087	Si-PNP	=2N5086: B>250	7e	-	BC214, BC416, BC560, 2SA872(A)..
2N5088	Si-NPN	AF, LN, 35V, 0,05A, 0,625W, B>300	7e	USA,Mic,Mot	BC169, BC184, BC239, BC549..
2N5089	Si-NPN	=2N5088: 30V, B>400	7e	-	BC169, BC184, BC239, BC549..
2N508A	Ge-PNP	=2N508: 30V, 0,2A, 0,2W, 4,5MHz	2a&	-	AC128, AC152..153, AC188
2N509	Ge-PNP	UHF, 30V, 0,04A, 750MHz	2a$	Wes	AF139, AF239(S)
2N5090	Si-NPN	VHF/UHF-Dr/Out, 55V, 0,4A, Pq>1,2W(400MHz)	49a	Mot,Rca,Sca	-
2N5091	Si-PNP	AF, Sw, 350/300V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	MJ5416, 2N5416
2N5092	Si-NPN	AF, Sw, 400/350V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	BSS49, BUX55, BUY59..60, 2N3439
2N5093	Si-PNP	AF, Sw, 400/350V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	MJ5416
2N5094	Si-PNP	AF, Sw, 450/400V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	MJ5416
2N5095	Si-NPN	AF, Sw, 500/400V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	BUX55, BUY59..60, 2N3439
2N5096	Si-PNP	AF, Sw, 500/450V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	MJ5416
2N5097	Si-NPN	AF, Sw, 600/450V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	BUY60
2N5098	Si-NPN	AF, Sw, 700/500V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	-
2N5099	Si-NPN	AF, Sw, 800/550V, 1A, 4W(Tc=25°)	2a$	Sca,Ssi,Stc	-
2N51	Ge-PNP	Sw, 50V, Ueb=50V, 8mA, 0,1W	-	Clv	(ASY48)
2N5100	Si-PNP	Sw, Pow, 450/400V, 1A, 10W, >20MHz	43a$	Sca,Ssi,Stc	-
2N5101	Si-NPN	Sw, Pow, 500/400V, 1A, 10W, >50MHz	43a$	Sca,Ssi,Stc	(BD410, BUV63, BUV93..95, BUW40A,B)
2N5102	Si-NPN	VHF-Pow, 100V, 3,3A, Pq=15W(136MHz)	49a*	Rca,Sem,Tix	BLY35, 2N3632
2N5103	N-FET	GenP, 25V, Idss>1mA, Up<4V	5h+	Isi,Nsc,++	2N5246, 2N5360, 2SK161
2N5104	N-FET	GenP, 25V, Idss>2mA, Up<4V	5h+	Isi,Nsc,++	2N5246, 2N5360, 2SK107
2N5105	N-FET	GenP, 25V, Idss>5mA, Up<4V	5h+	Isi,Nsc,++	BF256, BFS80, BFW11, 2N5485..
2N5106	Si-NPN	Sw, RadH, 60V, 0,6A, 0,8W, >250MHz	2a$	-	-
2N5107	Si-NPN	=2N5106: 0,36W, RadH	2a$	-	-
2N5108(A)	Si-NPN	UHF-Osc/Dr, 55V, 0,4A, Pq>1W(1GHz)	2a$	-	-
2N5109	Si-NPN	VHF/UHF-A, 40V, 0.5A, 2.5W, 1.5GHz	2a$	-	BFS50, MRF515, MRF629, 2N3948..
2N511	Ge-PNP	AF, Sw-Pow, 40V, Ueb=30V, 25A, 150W	23a$	USA,Tix	2N1651..53, 2N2285..87
2N5110	Si-PNP	AF, Sw, 40V, 1A, 0,5W, >1MHz	2a$	-	BC160..161, BCX60, BSV15..17..
2N5111	Si-PNP	=2N5110: 80V	2a$	-	BC161, BCX60, BSS18, BSV16..17..
2N5112	Si-PNP	=2N5110: 34W	49a$	-	-
2N5113	Si-PNP	=2N5110: 80V, 34W	49a$	-	-
2N5114	P-FET	Sw, 30V, Idss>30mA, Up<10V. 16/21nS	2a&	USA,Nsc,Phi	U304
2N5115	P-FET	Sw, 30V, Idss>15mA, Up<6V, 30/38nS	2a&	USA,Nsc,Phi	U305
2N5116	P-FET	Sw, 30V, 5mA 150Ω, Idss>5mA, Up<4V, 42/60nS	2a&	USA,Nsc,Phi	U306
2N5117	Si-PNP	Dual, LN, 45V, 10mA, 0,75W, >100MHz	81bs	Isi,Sol	BFX11, 2N3726, 2N40415..16
2N5118	Si-PNP	Dual, LN, 45V, 10mA, 0,75W, >100MHz	81bs	-	BFX11, 2N3726, 2N40415..16
2N5119	Si-PNP	Dual, LN, 45V, 10mA, 0,75W, >100MHz	81bs	-	BFX11, 2N3726, 2N40415..16
2N511A	Ge-PNP	=2N511: 60V	23a$	-	2N1651..53, 2N2285..87
2N511B	Ge-PNP	=2N511: 80V	23a$	-	2N1652..53, 2N2286..87
2N512	Ge-PNP	AF, Sw-Pow, 40V, Ueb=30V, 25A, 150W	23a$	USA,Tix	2N1651..53, 2N2285..87
2N5120	Si-PNP	=2N5117: 0,5W	81bs	-	(BFX11, 2N3726, 2N40415..1)
2N5121	Si-PNP	=2N5118: 0,5W	81bs	-	(BFX11, 2N3726, 2N40415..1)
2N5122	Si-PNP	=2N5119: 0,5W	81bs	-	(BFX11, 2N3726, 2N40415..1)

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2N5123	Si-PNP	=2N5117:0,75W	-		-
2N5124	Si-PNP	=2N5117:0,75W	-		-
2N5125	Si-PNP	=2N5117:0,75W	-		-
2N5126	Si-NPN	HF/AF,AGC,20V,0,03A,0,2W,>300MHz	8a	Fch,Sem,Tdy	BF240..241,BF254..255,BF594..595,..
2N5127	Si-NPN	HF/AF,20V,0,1A,0,2W,>150MHz	8a	USA,Mic,Nsc	BF240..241,BF254..255,BF594..595,..
2N5128	Si-NPN	GenP,15V,0,5A,0,3W,>200MHz	8a	USA,Mic,Nsc	BC337..338,BC635,2N2221..22(A)..
2N5129	Si-NPN	=2N5128:0,2W	8a	-	BC337..338,BC635,2N2221..22(A)..
2N512A	Ge-PNP	=2N512:60V	23a$	-	2N1651..53,2N2285..87
2N512B	Ge-PNP	=2N512:80V	23a$	-	2N1652..53,2N2286..87
2N513	Ge-PNP	AF,Sw-Pow,40V,Ueb=30V,25A,150W	23a$	USA,Tix	2N1651..53,2N2285..87
2N5130	Si-NPN	HF,30V,0,05A,0,2W,>450MHz	8a	USA,Mic,Nsc	BF314,BFS02,BF505,BF507,BF562..
2N5131	Si-NPN	GenP,20V,0,2A,0,2W,>100MHz	8a	USA,Nsc	BC168,BC183,BC238,BC548..
2N5132	Si-NPN	HF,20V,0,05A,0,2W,>200MHz	8a	USA,Mic,Nsc	BF240..241,BF254..255,BF594..595,..
2N5133	Si-NPN	GenP,20V,0,05A,0,2W,>40MHz	8a	USA,Mic,Nsc	BC168,BC183,BC238,BC548..
2N5134	Si-NPN	Sw,20V,0,1A,0,2W,<26/26nS	8a	USA,Mic,Nsc	BSS11..12,BSV89..92,2N2368..69(A),..
2N5135	Si-NPN	GenP,30V,0,2A,0,3W,>40MHz	8a	USA,Mic,Nsc	BC168,BC183,BC238,BC548..
2N5136	Si-NPN	GenP,30V,0,5A,0,3W,>40MHz	8a	USA,Mic,Nsc	BC337..338,BC635,BC637,BC639..
2N5137	Si-NPN	=2N5136:0,22W	8a	-	BC337..338,BC635,BC637,BC639..
2N5138	Si-PNP	GenP,50V,0,05A,0,2W,>30MHz	8a	USA,Mic,Nsc	BC212,BC257,BC307,BC557..
2N5139	Si-PNP	Sw,20V,0,1A,0,2W,<65/230nS	8a	USA,Mic,Nsc	BSW24,2N3209,2N4034..35,2N4125..26..
2N513A	Ge-PNP	=2N513:60V	23a$	-	2N1651..53,2N2285..87
2N513B	Ge-PNP	=2N513:80V	23a$	-	2N1652..53,2N2286..87
2N514	Ge-PNP	AF,Sw-Pow,40V,Ueb=30V,25A,150W	23a$	USA,Tix	2N1651..53,2N2285..87
2N5140	Si-PNP	Sw,5V,0,05A,0,2W,<35/35nS	8a	USA,Mic,Nsc	BSX36,2N4258,2N4313,2N5056..57
2N5141	Si-PNP	Sw,6V,0,1A,0,2W,<115/170nS	8a	USA,Mic,Nsc	BSW24,2N3209,2N4034..35,2N4125..26..
2N5142	Si-PNP	GenP,20V,0,5A,0,3W,<120/225nS	8a	USA,Mic,Nsc	BC327..328,BC636,2N2906..07(A)..
2N5143	Si-PNP	=2N5142:0,2W	8a	-	BC327..328,BC636,2N2906..07(A)..
2N5144	Si-NPN	Sw,RadH,50V,0,5A,0,36W,<45/65nS	2a$	Fch	-
2N5145	Si-NPN	=2N5144:0,8W,RadH	2a$	Fch	-
2N5146	Si-PNP	4xPNP,40V,1,5A,0,6W,250MHz	14-FLP/cs	Fch,Mot	-
2N5147	Si-PNP	=2N4999:1W	2a$	USA,Nsc,Tix	BSS17,2N5322
2N5148	Si-NPN	=2N4998:1W	2a$	USA,Nsc,Tix	BSS15,2N5320,2N5339
2N5149	Si-PNP	=2N5001:1W	2a$	USA,Nsc,Tix	BSS17,2N5322
2N514A	Ge-PNP	=2N514:60V	23a$	-	2N1651..53,2N2285..87
2N514B	Ge-PNP	=2N514:80V	23a$	-	2N1652..53,2N2286..87
2N515	Ge-NPN	AF/HF,18V,0,01A,0,05W,3MHz	?1a	Csr,Etc	(ASY28..29)
2N5150	Si-NPN	=2N5000:1W	2a$	USA,Nsc,Tix	BSS15,2N5320,2N5339
2N5151	Si-PNP	=2N5003:1W	2a$	USA,Sgs,Tix	BUY90,2N6192..93
2N5152	Si-NPN	=2N5002:1W	2a$	USA,Sgs,Tix	BUX34,BUY80,2N5338..39
2N5153	Si-PNP	=2N5005:1W	2a$	USA,Sgs,Tix	BSS44,BUY90,2N6192..93
2N5154	Si-NPN	100V,2A,1W	2a$	USA,Sgs,Tix	BFX34,BUX34,BUY80,2N5338..39
2N5155	Ge-PNP	Sw,Pow,140V,15A,106W	23a$	USA,Del,Mot	-
2N5156	Ge-PNP	Sw,Pow,100V,10A,93W	23a$	USA,Del,Mot	AL100..101,AUY37,2N2290,2N2293..
2N5157	Si-NPN	Sw,Pow,700/400V,3,5A,100W(Tc=75°)	23a$	USA,Mot,Tix	BUS11(A),BUX46(A),BUX48A,2SC3091,2SC3155..
2N5158	N-FET	Sw,Chopper,40V,Idss<100mA,Up<8V	2f&	Tdy	BFS74,BFS77,BSV78,2N3970..
2N5159	N-FET	Sw,Chopper,40V,Idss<100mA,Up<10V	2f&	Tdy	BFS74,BFS77,BSV78,2N3970..
2N516	Ge-NPN	AF/HF,18V,0,01A,0,05W,3MHz	?1a	Csr,Etc	(ASY28..29)
2N5160	Si-PNP	VHF/UHF-Dr/Out,60V,0,4A,Pq=1,2W(400MHz)	2a$	Mot,Ray	-
2N5161	Si-PNP	VHF-Pow,60V,1,5A,Pq=8,5W(175MHz)	49a*	Mot,Ray	-
2N5162	Si-PNP	VHF-Pow,60V,5A,Pq=35W(175MHz)	49a*	Mot,Ray	-
2N5163	N-FET	VHF,25V,Idss>1mA,Up<8V	8b	USA,Mic,Nsc	BF244..245,BFS72,BFW10,2N3823
2N5164	Thy-SOHz	50V,13A(Tc=67°),Igt/Ih<40/<50mA	29b$	Gen,Mot	MCR3818-2,2N3870,MCR3835-2,MCR63-2
2N5164..S167R	Thy-SOHz	=2N5164..S167:	29f&	-	→2N5164..S167
2N5165	Thy-SOHz	=2N5164:200V	29b$	-	MCR3818-4,2N3871,MCR3835-4,MCR63-4
2N5166	Thy-SOHz	=2N5164:400V	29b$	-	MCR3818-6,2N3872,MCR3835-6,MCR63-6
2N5167	Thy-SOHz	=2N5164:600V	29b$	-	MCR3818-8,2N3873,MCR3835-8,MCR63-8
2N5168	Thy-SOHz	=2N5164:	21b$	-	MCR3918-2,T12N100,MCR3935-2,MCR64-2
2N5168..S171R	Thy-SOHz	=2N5168..S171:	21f&	-	→2N5168..S171
2N5169	Thy-SOHz	=2N5165:	21b$	-	MCR3918-4,T12N200,MCR3935-4,MCR64-4
2N517	Ge-NPN	AF/HF,18V,0,01A,0,05W,3MHz	?1a	Csr,Etc	(ASY28..29)
2N5170	Thy-SOHz	=2N5165:	21b$	-	MCR3918-6,T12N400,MCR3935-6,MCR64-6
2N5171	Thy-SOHz	=2N5166:	21b$	-	MCR3918-8,T12N600,MCR3935-8,MCR64-8
2N5172	Si-NPN	GenP,25V,0,1A,0,36W,200MHz	7c	USA,Mic,Nsc	BC168,BC183,BC238,BC548..
2N5174	Si-NPN	GenP,90V,0,025A,0,36W	7c	Gen,Spr	BSS38,BSX21,2SC1890(A),2SC2240..

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2N5175	Si-NPN	GenP,130V,0,025A,0,2W	7c	Gen,Spr	BSS38,BSX21,2SC1890A,2SC2240..
2N5176	Si-NPN	GenP,130V,0,025A,0,36W	7c	-	BSS38,BSX21,2SC1890A,2SC2240..
2N5177	Si-NPN	HF-Pow,55V,4A,40W,>200MHz	60c*	Trw	-
2N5178	Si-NPN	HF-Pow,55V,8A,70W,>200MHz	60c*	Trw	-
2N5179	Si-NPN	VHF/UHF,LN,20V,0,05A,0,2W,1400MHz	5g	USA,Mot,Nsc	BF377..378,BF689,BF763,2N2857..
2N518	Ge-PNP	AF,Sw,45V,Ueb=30V,125mA,0,15W,11MHz	1a&	Csr,Etc	(ASY48,ASY76..77)
2N5180	Si-NPN	VHF,LN,30V,0,18W,900MHz	5g	USA,Rca,Tix	BF314,BFS02,BFS05,BFS07,BFS62..
2N5181	Si-NPN	HF/AF,45V,0,05A,0,18W,700MHz	5k	USA,Nsc,Rca	BF198..199,BF224..225,BF310..311,..
2N5182	Si-NPN	HF/AF,45V,4mA,0,18W,700MHz	5k	USA,Nsc,Rca	BF198..199,BF224..225,BF310..311,..
2N5183	Si-NPN	GenP,18V,1A,0,5W,<75/575nS	2a$	USA,Rca	BC337..338,BC635,2N2221..22(A)..
2N5184	Si-NPN	Vid,-/120V,0,05A,0,5W,100MHz	2a$	Rca,Sem	BF297..299,BFT57..59,2SC3467..
2N5185	Si-NPN	=2N5184:1W	2a$o	-	BF297..299,BFT57..59,2SC3467..
2N5186	Si-NPN	Sw,10V,0,3A,0,3W,600MHz,<25/25nS	2a$	Rca,Sem	BSS10..12,BSX19..20,2N3261..
2N5187	Si-NPN	Fast-Sw,25V,0,5A,0,3W,600MHz,<12/14nS	2a$	Rca,Sca,Sem	BSS10,BSX26,BSX39,2N3261
2N5188	Si-NPN	Sw,60V,1A,0,8W,325MHz,<35/50nS	2a$	USA,Rca	BSS27,BSV77,BSV95,2SC1635..
2N5189	Si-NPN	Sw,60V,1A,1W,>250MHz,<40/70nS	2a$	USA,Rca,Tix	BSS27,BSV77,BSV95,2SC1635..
2N519(A)	Ge-PNP	AF,Sw,15V,0,1W,>0,5MHz,A:25V,0,15W,1500/-nS	2a	USA	ASY26..27,ASY76..77
2N5190	Si-NPN	AF,Sw-Pow,40V,4A,40W,>2MHz	14h$	Mot,Nsc,Sgs	BD185,BD437,BD785,MJE240..244..
2N5191	Si-NPN	=2N5190:60V	14h$	-	BD187,BD439,BD787,MJE240..244..
2N5192	Si-NPN	80V,4A,40W,2MHz	14h$	-	BD189,BD441,BD789,MJE240..244..
2N5193	Si-PNP	AF,Sw-Pow,40V,4A,40W,>2MHz	14h$	Mot,Nsc,Sgs	BD186,BD438,BD786,MJE250..254..
2N5194	Si-PNP	=2N5193:60V	14h$	-	BD188,BD440,BD788,MJE250..254..
2N5195	Si-PNP	=2N5193:80V	14h$	-	BD190,BD442,BD788,MJE250..254..
2N5196	N-FET	Dual,LN,50V,Idss>0,7mA,Up<4V	81bx	Isi,Nsc,Six	U401
2N5197	N-FET	Dual,LN,50V,Idss>0,7mA,Up<4V	81bx	-	U401
2N5198	N-FET	Dual,LN,50V,Idss>0,7mA,Up<4V	81bx	-	U402,U403
2N5199	N-FET	Dual,LN,50V,Idss>0,7mA,Up<4V	81bx	-	U404
2N52	Ge-PNP	Sw,50V,Ueb=50V,8mA,0,12W	-	Clv	(ASY48)
2N520(A)	Ge-PNP	AF,Sw,15V,0,1W,>3MHz,A:25V,0,15W,1100/-nS	2a	USA	ASY26..27,ASY76..77
2N5200	Si-NPN	UHF,RadH,20V,0,1A,0,3W,>900MHz	2a$	Fch,Sca	-
2N5201	Si-NPN	UHF,RadH,20V,0,1A,0,3W,>1100MHz	2a$	-	-
2N5202	Si-NPN	AF,Sw-Pow,100V,4A,35W,>60MHz	22a$	USA,Rca	BDV10..12,2SD772
2N5203	Si-NPN	=BFW35	2a	-	→BFW35
2N5204	Thy-50Hz	600V,22A(Tc=40°),Igt/Ih<40/<100mA	21b$	USA,Tho,Tag	C228M,2N3899,MCR3935-8,C35M..
2N5205	Thy-50Hz	=2N5204:800V	21b$	-	MCR3935-10,C35N,MCR64-10,TAG35-800
2N5206	Thy-50Hz	=2N5204:1000V	21b$	-	C35P,MCR64-10,TAG35-1000
2N5207	Thy-50Hz	=2N5204:1200V	21b$	-	-
2N5208	Si-PNP	FM/VHF,LN,30V,0,05A,0,35W,>300MHz	7f	Mot	BF324,BF414,BF506,BF914,BF936..
2N5209	Si-NPN	AF,LN,50V,0,05A,0,625W,80MHz	7e	USA,Fer,Mot	BC184,BC413..414,BCS50,2SC2240..
2N521(A)	Ge-PNP	AF,Sw,15V,0,1W,>8MHz,A:25V,0,15W,400/-nS	2a	USA	ASY26..27
2N5210	Si-NPN	AF,LN,50V,0,05A,0,625W,80MHz	7e	-	BC184,BC413..414,BCS50,2SC2240..
2N5211	Si-NPN	VHF-Dr,80V,0,6A,0,8W,>200MHz	2a*	Itt	BFS23,BLY34
2N5212	Si-NPN	VHF-Dr/Out,80V,0,6A,7,5W,>200MHz	43a*	Itt	-
2N5213	Si-NPN	VHF/UHF-Dr/Out,70V,0,5A,Pq=3W(200MHz)	43a*	Itt	-
2N5214	Si-NPN	VHF-Pow,95V,5A,Pq=30W(150MHz)	-	Itt	(BLY94,2SC2182)
2N5215	Si-NPN	VHF-Pow,70V,1A,Pq=10W(200MHz)	49a*	Itt,Tix	BLY60,2N3632
2N5216	Si-NPN	VHF/UHF-Pow,80V,1,5A,Pq=15W(400MHz)	-	Itt	(BLW94,BLX94,MRF323,2SC1118)
2N5217	Si-NPN	VHF/UHF-Dr/Out,80V,0,5A,Pq=4W(400MHz)	-	Itt	(BLW94,BLX94,MRF323,2SC1118)
2N5218	Si-NPN	Sw,Pow,220/200V,10A,50W(Tc=100°)	49a$	USA	2N5540
2N5219	Si-NPN	GenP,20V,0,1A,0,35W,>150MHz	7e	USA,Mot,Tix	BC168,BC183,BC238,BC548..
2N522	Ge-PNP	AF,Sw,15V,0,1W,>15MHz	2a	USA	ASY26..27
2N5220	Si-NPN	GenP,15V,0,5A,0,625W,>100MHz	7e	USA,Mot,Tix	BC337..338,BC635,BC637,BC639..
2N5221	Si-PNP	GenP,15V,0,5A,0,35W,>100MHz	7e	USA,Mot,Tix	BC327..328,BC636,BC638,BC640..
2N5222	Si-NPN	AM/FM,TV-IF,20V,0,05A,>450MHz	7f	USA,Mot,Tix	BF198..199,BF224..225,BF310..311,..
2N5223	Si-NPN	GenP,25V,0,1A,0,625W,>150MHz	7e	USA,Mot,Tix	BC168,BC183,BC238,BC548..
2N5224	Si-NPN	AF,Sw,25V,0,2A,0,625W,<45/60nS	7e	USA,Mot	BSS10..12,BSX19..20,2N2368..69(A),..
2N5225	Si-NPN	GenP,25V,0,5A,0,625W,>50MHz	7e	USA,Mot,Tix	BC337..338,BC635,BC637,BC639..
2N5226	Si-PNP	GenP,25V,0,5A,0,625W,>50MHz	7e	USA,Mot,Tix	BC327..328,BC636,BC638,BC640..
2N5227	Si-PNP	GenP,30V,0,05A,0,625W,>100MHz	7e	USA,Mot,Tix	BC213,BC258,BC308,BC558..
2N5228	Si-PNP	AF,Sw,5V,0,05A,0,625W,<75/140nS	7e	USA,Mot	BSW24,BSX36,2N4258,2N4313..
2N5229	Si-PNP	Chopper,15/10/15V,0,05A,0,5W	2a$	Mot,Ssi	2N2944
2N522A	Ge-PNP	AF,Sw,15V,0,15W,300/-nS	2a	USA	ASY26..27
2N523(A)	Ge-PNP	AF,Sw,15V,0,1W,>21MHz,A:20V,0,15W,200/-nS	2a	USA	(ASY26..27)
2N5230	Si-PNP	Chopper,30/20/30V,0,05A,0,5W	2a$	Mot,Ssi	2N2945

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2N5231	Si-PNP	Chopper,50/30/50V,0,05A,0,5W	2a$	Mot,Ssi	2N2946
2N5232(A)	Si-NPN	GenP,LN,70V,0,1A,0,36W,>250MHz	7c,7a	USA,Mic,Nsc	2SC1775(A),2SC2240,2SC2389,2SC2459,..
2N5233	Si-NPN	GenP,80V,0,1A,0,33W,B>100	7c	Csr	BC546,2SC1890(A),2SD755..756(A)..
2N5234	Si-NPN	=2N5233:B>250	7c	-	BC546,2SC1890(A),2SD755..756(A)..
2N5235	Si-NPN	=2N5233:B>400	7c	-	BC546,2SC1890(A),2SD755..756(A)..
2N5236	Si-NPN	HF-Osc,AF,40V,0,15A,0,6W,>500MHz,RadH	2a$	Fch,Sca,Ssi	-
2N5237	Si-NPN	Sw,150V,5A,8,75W(Tc=25°),25MHz	2a$	USA	BUY80,2N4879
2N5238	Si-NPN	=2N5237:200V	2a$	-	BUY48..49
2N5239	Si-NPN	Sw,Pow,300/225V,5A,100W,>2MHz	23a$	RCA	BU606..608,BUX16A..C,2SC2624..
2N524(A)	Ge-PNP	AF,Sw,45V,0,5A,0,225W,1,5MHz	2a&	USA,Mot,Tix	ASY76..77
2N5240	Si-NPN	375/300V,5A,100W,>2MHz	23a$	-	BU606..608,BUX16B..C,BUX48A,2SC2624..
2N5241	Si-NPN	Sw,Pow,400/400V,5A,125W(Tc=62°)	23a$	USA,Mot,Tix	BUX16C,BUX18C,BUX45,BUX48A,2SD640..
2N5242	Si-PNP	Sw,20V,0,5A,0,5W,>170MHz,<45/95nS	8a	Fch	2N3467..68,2N5022..23,2SA742..
2N5243	Si-PNP	=2N5242:30V	8a	-	2N3467..68,2N5022..23,2SA742..
2N5244	Si-PNP	Sw,RadH,40V,0,1A,0,36W,<55/150nS	2a$	Fch,Itt,Sgs	-
2N5245	N-FET	VHF,30V,Idss>5mA,Up<6V	7f	USA,Isi,Mot	BF244..245,BFS80,BFW11,2N4416..
2N5246	N-FET	VHF,30V,Idss>1,5mA,Up<4V	7f	-	2SK107,2SK161
2N5247	N-FET	VHF,30V,Idss>8mA,Up<8V	7f	-	BF244..245,BFW10
2N5248	N-FET	VHF,30V,Idss>4mA,Up<8V	7e	USA,Isi,Tix	BF244..245,BFS72,2N3823
2N5249(A)	Si-NPN	AF,LN,70V,0,1A,0,36W	7c	Gen,Sem,Spr	2SC1775(A),2SC2240,2SC2389,2SC2459,..
2N525(A)	Ge-PNP	AF,Sw,45V,0,5A,0,225W,2MHz	2a&	USA,Mot,Tix	ASY76..77
2N5250	Si-NPN	Sw,Pow,125/100V,90A,350W,>10MHz	49a$	USA	2N6309..11
2N5251	Si-NPN	=2N5250:180/150V	49a$	-	2N6309..11
2N5252	Si-NPN	Sw,Vid,300/300V,1A,1W,>30MHz,B>40	2a$	Ssi,Stc	BFQ38..40,BSS48..49,2N3439..40
2N5253	Si-NPN	=2N5252:B>80	2a$	-	BFQ38..40,BSS48..49,2N3439..40
2N5254	Si-PNP	Dual,LN,40V,0,05A,0,43W,>40Mhz	81bs	Fch,Isi	BFX11,2N3726,2N4015..15
2N5254..56/78	Si-PNP	=2N5254..56:0,5W,>60MHz	81bs	-	BFX11,2N3726,2N4015..15
2N5255	Si-PNP	Dual,LN,40V,0,05A,0,43W,>40MHz	81bs	-	BFX11,2N3726,2N4015..15
2N5256	Si-PNP	Dual,LN,40V,0,05A,0,43W,>40MHz	81bs	-	BFX11,2N3726,2N4015..15
2N526(A)	Ge-PNP	AF,Sw,45V,0,5A,0,225W,2,5MHz	2a&	USA,Mot,Tix	ASY76..77
2N5262	Si-NPN	Sw,75V,2A,1W,350MHz,18/35nS	2a$	USA,Rca	BSS14,2N3507
2N5264	Si-NPN	Sw,Pow,400/180V,7A,87W,>50MHz	23a$	USA	BU606..608,BUX18B..C,BUX98A,2SC2656..
2N5265	P-FET	GenP,60V,Idss>0,5mA,Up<3V	5g+	Isi,Mot	-
2N5266	P-FET	GenP,60V,Idss>0,8mA,Up<3V	5g+	Isi,Mot	-
2N5267	P-FET	GenP,60V,Idss>1,5mA,Up<6V	5g+	Isi,Mot	2N5463..64
2N5268	P-FET	GenP,60V,Idss>2,5mA,Up<6V	5g+	Isi,Mot	2N5463..64
2N5269	P-FET	GenP,60V,Idss>4mA,Up<8V	5g+	Isi,Mot	2N5465
2N527(A)	Ge-PNP	AF,Sw,45V,0,5A,0,225W,3,5MHz	2a&	USA,Mot,Tix	ASY76..77
2N5270	P-FET	GenP,60V,Idss>7mA,Up<8V	5g+	Isi,Mot	-
2N5271	Si-NPN	Sw,Avalanche,280V,5A(ss),0,6W	2a$	Mot,Sca	-
2N5272	Si-NPN	Sw,40V,0,2A,0,36W,>500MHz,<23/28nS	2a$	Sty	BSS10..11,BSX19..20,2N2368..69(A),..
2N5273	Triac	200V,25A,Igt/Ih<150/<100mA	21b$	TI	2N5806,BTX94/200
2N5274	Triac	=2N5273:400V	21b$	-	2N5807,BTX94/400
2N5275	Triac	=2N5273:600V	21b$	-	2N5809,BTX94/600
2N5276	Si-NPN	Sw,RadH,25V,0,36W,>600MHz	2a$	TI	-
2N5277	N-FET	Sw,150V,Idss>2,5mA,Up<7V	2b&	Six,Tix	-
2N5278	N-FET	Sw,150V,Idss>10mA,Up<10V	2b&	Six,Tix	-
2N5279	Si-NPN	Sw,Vid,400/300V,1A,1W,>15MHz	2a$	Sca,Ssi,Stc	BFQ40,BSS49,2N3439
2N528	Ge-PNP	AF,Sw,40V,Ueb=40V,1A,2,5W,>4MHz	2a&	Wes	2SB493
2N5280	Si-NPN	=2N5279:15W	43a$	-	(BD410,BUW40(A,B),TIP49..50,..)
2N5281	Si-PNP	Sw,Vid,175V,1A,2W(Tc=100°),>20MHz	2a$	Sca,Ssi,Stc	BFT19(A,B),BFT28A..C,2N5415..16..
2N5282	Si-PNP	=2N5281:325/300V	2a$	-	BFT19B,2N5416,MJ5416
2N5284	Si-NPN	Sw,Pow,120/100V,5A,50W(Tc=50°),>60MHz	49a	USA	2N5339
2N5285	Si-NPN	Sw,Pow,120/100V,5A,50W(Tc=50°),>70MHz	49a	-	2N5339
2N5286	Si-PNP	Sw,Pow,120/100V,5A,50W(Tc=50°),>60MHz	49a	USA	-
2N5287	Si-PNP	Sw,Pow,120/100V,5A,50W(Tc=50°),>70MHz	49a	-	-
2N5288	Si-NPN	Sw,Pow,120/100V,10A,100W(Tc=50°),>30MHz	49a	USA	2N5542
2N5289	Si-NPN	Sw,Pow,120/100V,10A,100W(Tc=50°),>40MHz	49a	-	2N5542
2N529	Ge-P/N	AF-Complement.GenP,15V,0,025A,a>15	2a	Csr,Etc	(AC127+AC128,AC127+AC152)
2N5290	Si-PNP	Sw,Pow,120/100V,10A,100W(Tc=50°),>30MHz	49a	USA	-
2N5291	Si-PNP	Sw,Pow,120/100V,10A,100W(Tc=50°),>40MHz	49a	-	-
2N5292	Si-PNP	Sw,RadH,12V,0,1A,0,36W,>800MHz	2a$	Fch,Spe,Sty	-
2N5293	Si-NPN	AF,Sw-Pow,80V,4A,36W,>0,8MHz	17j$	USA,Mic,Nsc	BD243B,BD537,BD539B,BD951,TIP31C...
2N5294	Si-NPN	AF,Sw-Pow,80V,4A,36W,>0,8MHz	17j$	-	BD243B,BD537,BD539B,BD951,TIP31C...

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2N5295	Si-NPN	AF,Sw-Pow,60V,4A,36W,>0,8MHz	17j$	-	BD243A,BD535,BD539A,BD949,TIP31C…
2N5296	Si-NPN	AF,Sw-Pow,60V,4A,36W,>0,8MHz	17j$	-	BD243A,BD535,BD539A,BD949..
2N5297	Si-NPN	AF,Sw-Pow,80V,4A,36W,>0,8MHz	17j$	-	BD243B,BD537,BD539B,BD951,TIP31C…
2N5298	Si-NPN	AF,Sw-Pow,80V,4A,36W,>0,8MHz	17j$	-	BD243B,BD537,BD539B,BD951,TIP31C…
2N53	Ge-PNP	Sw,50V,Ueb=50V,8mA,0,1W,5MHz	-	Clv	(ASY48)
2N530	Ge-P/N	=2N529:a>20	2a	Csr,Etc	(AC127+AC128,AC127+AC152)
2N5301	Si-NPN	AF,Sw-Pow,40V,30A,200W,>2MHz	23a$	USA,Mot,Rca	BDY29,MJ802,2N3771,2SD630,2SD797
2N5302	Si-NPN	=2N5301:60V	23a$	-	BDY29,MJ802,2N5886,2SD797
2N5303	Si-NPN	=2N5301:80V	23a$	-	BDY29,MJ802,2N5886,2SD797
2N5304	Si-NPN	Sw,Pow,50V,10A,25W(Tc=125°),>100MHz	49a$	Mot,Stc	-
2N5305	Si-NPN-Darl	AF-Pre,25V,0,3A,0,4W,B>2000,>60MHz	7c	USA,Mic,Nsc	BC517,BC617,MPSA13..14,2SD892..
2N5306	Si-NPN-Darl	=2N5305:B>7000	7c	-	BC517,BC617,MPSA13..14,2SD892..
2N5306A	Si-NPN-Darl	=2N5305:B>7000,ra	7c	-	-
2N5307	Si-NPN-Darl	AF-Pre,40V,0,3A,0,4W,B>2000,>60MHz	7c	-	BC517,BC617,MPSA25..29,2SD892A..
2N5308	Si-NPN-Darl	40V,0.3A,0.4W,B>7000	7c	-	BC517,BC617,MPSA25..29,2SD892A..
2N5308A	Si-NPN-Darl	=2N5307:B>7000,ra	7c	-	-
2N5309	Si-NPN	AF,70V,0,1A,0,36W,B>60	7c	Gen,Sem,Spr	BC174,BC182,BC190,BC546..
2N531	Ge-P/N	=2N529:a>25	2a	Csr,Etc	(AC127+AC128,AC127+AC152)
2N5310	Si-NPN	=2N5309:B>100	7c	-	BC174,BC182,BC190,BC546..
2N5311	Si-NPN	=2N5309:B>250	7c	-	BC174,BC182,BC190,BC546..
2N5312	Si-PNP	Sw,Pow,80V,10A,50W(Tc=100°),>30MHz	49a$	USA	2N5290..91
2N5313	Si-NPN	Sw,Pow,80V,10A,50W(Tc=100°),>30MHz	49a$	USA	2N5288..89
2N5314	Si-PNP	=2N5312:100V	49a$	-	2N5290..91
2N5315	Si-NPN	=2N5313:100V	49a$	-	2N5288..89
2N5316	Si-PNP	=2N5312:Iso	49a	-	2N5290..91
2N5317	Si-NPN	=2N5313:Iso	49a	-	2N5288..89
2N5318	Si-PNP	=2N5312:Iso,100V	49a	-	2N5290..91
2N5319	Si-NPN	=2N5313:Iso,100V	49a	-	2N5288..89
2N532	Ge-P/N	=2N529:a>30	2a	Csr,Etc	(AC127+AC128,AC127+AC152)
2N5320	Si-NPN	AF,Sw,100V,2A,10W(Tc=25°),<80/800nS	2a$	USA,Rca,Sgs	BSS15,BSV84,2N4239,2SD854
2N5321	Si-NPN	=2N5320:75V	2a$	-	BSS15,BSV84,2N4238..39,2SD854
2N5322	Si-PNP	AF,Sw,100V,2A,10W(Tc=25°),<100/1000nS	2a$	USA,Rca,Sgs	BSS17
2N5323	Si-PNP	=2N5322:75V	2a$	-	BSS17..18,2N4236
2N5324	Ge-PNP	TV-HD,250V,10A,56W	23a$	Gpd,Mot,Sem	AU113,AU213
2N5325	Ge-PNP	=2N5324:325V	23a$	-	AU106,AU109,AU111..112
2N5326	Si-NPN	Sw,Pow,100V,5A,20W(Tc=100°),>80MHz	49a	USA,Tix	2N5002,2N5004,2N5284..85
2N5327	Si-NPN	Sw,100V,10A,5W(Tc=100°),>100MHz	2a$	USA,Tix	BUY82
2N5328	Si-NPN	Sw,Pow,100V,10A,30W(Tc=100°),>100MHz	49a	USA,Tix	2N5348..49
2N5329	Si-NPN	Sw,Pow,150V,20A,65W(Tc=100°),>80MHz	49a	USA,Tix	-
2N533	Ge-P/N	=2N529:a>35	2a	Csr,Etc	(AC127+AC128,AC127+AC152)
2N5330	Si-NPN	Sw,Pow,150V,30A,80W(Tc=100°),>80MHz	49a	USA,Tix	-
2N5331	Si-NPN	Sw,Pow,150V,30A,100W(Tc=100°),>80MHz	49a	USA,Tix	2N2825
2N5332	Si-PNP	Sw,RadH,20V,0,1A,0,36W,>800MHz	2a$	Mot,Tix	-
2N5333	Si-PNP	AF,Sw,100V,2A,1W,150/450nS	2a$	USA,Tix	BSS17,BSS44,2N5322
2N5334	Si-NPN	AF,Sw,60V,3A,6W(Tc=25°),<100/1050nS	2a$	USA,Mot	BSX62..64,2N4237..39,2N5339,2SC2214
2N5335	Si-NPN	=2N5334:80V	2a$	-	BSX63..64,2N4238..39,2SC2214
2N5336	Si-NPN	AF,Sw,80V,5A,6W(Tc=25o),B>30	2a$	USA,Mot,Nsc	BFT32..34,BUX34,BUY80,2N4895..97
2N5337	Si-NPN	=2N5336:B>60	2a$	-	BFT32..34,BUX34,BUY80,2N4895..97
2N5338	Si-NPN	=2N5336:100V	2a$	-	BFT33..34,BUX34,BUY80,2N4895..97
2N5339	Si-NPN	=2N5336:100V,B>60	2a$	-	BFT33..34,BUX34,BUY80,2N4895..97
2N534	Ge-PNP	AF,Sw,50V,0,025A,0,025W	37e	Etc,Nsc,Phc	(ASY48,ASY77)
2N5344	Si-PNP	AF,Sw-Pow,250/250V,1A,40W,>60MHz	22a$	Mot,Stc	BUX66A..C,2N6421,2SA1009(A),2SA1397
2N5345	Si-PNP	=2N5344:300/300V	22a$	-	BUX66A..C,2N6421,2SA1009(A),2SA1397
2N5346	Si-NPN	=2N5336:7A,60W	49a	USA,Mot	2N5339
2N5347	Si-NPN	=2N5337:7A,60W	49a	USA,Mot	2N5339
2N5348	Si-NPN	=2N5338:7A,60W	49a	USA,Mot	2N5339
2N5349	Si-NPN	=2N5339:7A,60W	49a	USA,Mot	2N5339
2N535(A,B)	Ge-PNP	AF,Sw,20/20/20V,0,02A,0,05W,2MHz	37e	Csr,Etc	(ASY26..27)
2N5350	Si-NPN	Sw,Pow,125/100V,350W,>10MHz	-	-	-
2N5351	Si-NPN	Sw,Pow,180/150V,350W,>10MHz	-	-	-
2N5354	Si-PNP	GenP,25V,0,3A,0,36W,250MHz,B>40	7c	USA,Mic,Nsc	BC327..328,BC636,BC638,BC640..
2N5355	Si-PNP	=2N5354:B>100	7c	-	BC327..328,BC636,BC638,BC640..
2N5356	Si-PNP	=2N5354:B>250	7c	-	BC327..328,BC636,BC638,BC640..
2N5357	Si-PNP	Sw,Pow,300/300V,3A,30W(Tc=75°),>50MHz	43a$	Mot,Mic,Stc	(2SA1009(A),2SA1236,2SA1397)

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2N5358	N-FET	GenP,LN,40V,Idss>0,5mA,Up<3V	5m+	USA,Mot,Tix	2N4339,2SK83,2SK193,2SK195
2N5359	N-FET	GenP,LN,40V,Idss>0,8mA,Up<4V	5m+	USA,Mot,Tix	-
2N536	Ge-PNP	AF,Sw,20/20/20V,0,03A,0,05W,2MHz	37e	Etc	(ASY26..27)
2N5360	N-FET	GenP,LN,40V,Idss>1,5mA,Up<4V	5m+	USA,Mot,Tix	2N5246
2N5361	N-FET	GenP,LN,40V,Idss>2,5mA,Up<6V	5m+	USA,Mot,Tix	BF256A,BFS71,2N3822,2N4221,2N5458
2N5362	N-FET	GenP,LN,40V,Idss>4mA,Up<7V	5m+	USA,Mot,Tix	BF256A,BFS80,BFW11,2N4416..
2N5363	N-FET	GenP,LN,40V,Idss>7mA,Up<8V	5m+	USA,Mot,Tix	BFW10
2N5364	N-FET	GenP,LN,40V,Idss>9mA,Up<8V	5m+	USA,Mot,Tix	BF244C..245C,BFW10
2N5365	Si-PNP	=2N5354:40V	7c	USA,Mic,Nsc	BC327,BC636,BC638,BC640..
2N5366	Si-PNP	=2N5355:40V	7c	USA,Mic,Nsc	BC327,BC636,BC638,BC640..
2N5367	Si-PNP	=2N5356:40V	7c	USA,Mic,Nsc	BC327,BC636,BC638,BC640..
2N5368	Si-NPN	GenP,60V,0,5A,0,36W,<40/350nS	7a	Gen,Mic,Nsc	BC337A,BC637,BSV59,2N2221..22(A)..
2N5369	Si-NPN	GenP,60V,0,5A,0,36W,<40/350nS	7a	-	BC337A,BC637,BSV59,2N2221..22(A)..
2N537	Ge-PNP	VHF/UHF,30V,0,1A,600MHz	2a$	Wes	(AF139,AF239(5))
2N5370	Si-NPN	GenP,60V,0,5A,0,36W,<40/400nS	7a	-	BC337A,BC637,BSV59,2N2221..22(A)..
2N5371	Si-NPN	GenP,40V,0,5A,0,36W,<40/400nS	7a	-	BC337,BC637,BSV59,2N2221..22(A),..
2N5372	Si-PNP	GenP,60V,0,5A,0,36W,<50/150nS	7a	Gen,Mic,Nsc	BC327A,BC638,BSW24,2N2906..07(A)..
2N5373	Si-PNP	GenP,60V,0,5A,0,36W,<50/150nS	7a	-	BC327A,BC638,BSW24,2N2906..07(A)..
2N5374	Si-PNP	GenP,60V,0,5A,0,36W;<50/175nS	7a	-	BC327A,BC638,BSW24,2N2906..07(A)..
2N5375	Si-PNP	GenP,40V,0,5A,0,36W,<50/175nS	7a	-	BC327,BC638,BSW24,2N2906..07(A),..
2N5376	Si-NPN	GenP,60V,0,5A,0,36W,>300MHz,B>120	7a	Itt,Sem,Spr	BC337A,BC637,BSV59,2N2221..22(A)..
2N5377	Si-NPN	GenP,60V,0,5A,0,36W,>300MHz,B>100	7a	Itt,Sem,Spr	BC337A,BC637,BSV59,2N2221..22(A)..
2N5378	Si-PNP	GenP,40V,0,5A,0,36W,>200MHz,B>120	7a	Itt,Sem,Spr	BC327A,BC638,BSW24,2N2906..07(A)..
2N5379	Si-PNP	GenP,40V,0,5A,0,36W,>200MHz,B>100	7a	Itt,Sem,Spr	BC327A,BC638,BSW24,2N2906..07(A)..
2N538(A)	Ge-PNP	Sw,Pow,80V,Ueb=28V,3,5A,34W,B>20	37b$	Gpd,Sem,Stc	-
2N5380	Si-NPN	GenP,60V,0,2A,0,36W,<70/225nS	7a	Itt,Sem,Spr	BC546,BSV59,BSX49,2N2221..22(A),..
2N5381	Si-NPN	GenP,60V,0,2A,0,36W,<70/250nS	7a	Itt,Sem,Spr	BC546,BSV59,BSX49,2N2221..22(A),..
2N5382	Si-PNP	GenP,40V,0,2A,0,36W,<70/260nS	7a	Itt,Sem,Spr	BC307,BC556,BSW24,2N2906..07(A),..
2N5383	Si-PNP	GenP,40V,0,2A,0,36W,<70/300nS	7a	Itt,Sem,Spr	BC307,BC556,BSW24,2N2906..07(A),..
2N5384	Si-PNP	Sw,Pow,100/80V,5A,30W(Tc=100°)	50g	USA,Tix	2N5003,2N5005,2N5286..87
2N5385	Si-PNP	=2N5384:	?49a$	USA,Tix	2N5003,2N5005,2N5286..87
2N5386	Si-PNP	Sw,Pow,100/80V,12A,50W(Tc=100°)	49a$	USA,Tix	2N5038,2N5290..91
2N5387	Si-NPN	Sw,Pow,200/200V,7,5A,100W(Tc=100°)	49a$	Sol,Stc,Tix	2N5540,2N6547
2N5388	Si-NPN	=2N5387:250/250V	49a$	-	2N5540,2N6547
2N5389	Si-NPN	=2N5387:300/300V	49a$	-	2N5540,2N6547
2N538M	Ge-PNP	Sw,Pow,80V,Ueb=28V,4,5A,34W,B>20	37b$	Gpd,Sem,Stc	-
2N539(A)	Ge-PNP	=2N538:B>30	37b$	Gpd,Sem,Stc	-
2N5390	Si-NPN-Darl	Sw,120V,2A,1W,B>2000	5t	USA,Tix	-
2N5391	N-FET	GenP,LN,70V,Idss>0,5mA,Up<2V	2b&	Sol,Tsc	-
2N5392	N-FET	GenP,LN,70V,Idss>1mA,Up<2,5V	2b&	Sol,Tsc	-
2N5393	N-FET	GenP,LN,70V,Idss>2,5mA,Up<3V	2b&	Sol,Tsc	-
2N5394	N-FET	GenP,LN,70V,Idss>4mA,Up<4V	2b&	Sol,Tsc	-
2N5395	N-FET	GenP,LN,70V,Idss>5,5mA,Up<4V	2b&	Sol,Tsc	-
2N5396	N-FET	GenP,LN,70V,Idss>7,5mA,Up<5V	2b&	Sol,Tsc	-
2N5397	N-FET	VHF/UHF,25V,Idss>10mA,Up<6V	5h+	USA,Isi,Tix	BF256C,2N5486
2N5398	N-FET	VHF/UHF,25V,Idss>5mA,Up<6V	5h+	USA,Isi,Tix	BF256A,B,2N5486
2N5399	Si-NPN	Sw,RadH,25V,0,1A,0,36W,>600MHz	2a$	TI	-
2N54	Ge-PNP	AF,45V,10mA,0,2W,0,5MHz	24e	Whs	ASY48,2SB56A
2N540(A)	Ge-PNP	=2N538:B>45	37b$	Gpd,Sem,Stc	-
2N5400	Si-PNP	GenP,130V,0,6A,0,625W,>100MHz	7e	USA,EUR,Tos	BF491,2SA840,2SA1221..22,2SA1319..
2N5400S	Si-PNP	-	35	Kec	→2N5400S
2N5401	Si-PNP	160V,0.6A,0.31W	7e	EUR,USA,Tos	BF491..493,2SA1221..22,2SA1319..
2N5401C	Si-PNP	=2N5400:160V	7c	Kec	→2N5401
2N5401S	Si-PNP	-	35	Kec	→2N5401S
2N5404	Si-PNP	Sw,80V,5A,1W,>40MHz,B>20	2a$	USA,Tix	BFT35..37,BSS46,2N6190..93
2N5405	Si-PNP	=2N5404:100V	2a$	-	BFT36..37,2N6192..93
2N5406	Si-PNP	=2N5404:B>40	2a$	-	BFT35..37,BSS46,2N6190..93
2N5407	Si-PNP	=2N5404:100V,B>40	2a$	-	BFT36..37,2N6192..93
2N5408	Si-PNP	Sw,Pow,80V,5A,30W(Tc=100°),B>20	49a$	-	2N5003,2N5005,2N5286..87
2N5409	Si-PNP	=2N5408:100V	49a$	-	2N5003,2N5005,2N5286..87
2N541(A)	Si-NPN	AF/HF,15V,0,025A,0,2W,>10MHz	2a	USA,Tix	BC168,BC183,BC238,BC548..
2N5410	Si-PNP	=2N5408:B>40	49a$	-	2N5003,2N5005,2N5286..87
2N5411	Si-PNP	=2N5408:100V,B>40	49a$	-	2N5003,2N5005,2N5286..87
2N5412	Si-NPN	Sw,Pow,80V,15A,100W,>60MHz	49a$	USA,Tix	(2N2815..16,2N2819..20)

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2N5413	Si-NPN	Sw,60V,2A,1W,>250MHz,<42/85nS	2a$	Csr,Sca,Ssi	BSS14,2N5262
2N5414	Si-NPN	=2N5413:80V	2a$	-	BSS14,2N5262
2N5415(S)	Si-PNP	Sw,Vid,200V,1A,10W(Tc=25°),>15MHz	2a$	USA,EUR	BFT19(A,B),BFT28A..C),MJ5415..16
2N5416	Si-PNP	Sw,Vid,350V,1A,10W(Tc=25°),>50MHz	2a$	-	BFT19B
2N5417	Si-NPN	Sw,RadH,40V,0,5A,0,5W,>250MHz	2a$	Sty	-
2N5418	Si-NPN	GenP,25V,0,5A,0,4W,250MHz,B>40	7c	USA,Gen,Mic	BC337..338,BC635,BC637,BC639..
2N5419	Si-NPN	=2N5418:B>100	7c	-	BC337..338,BC635,BC637,BC639..
2N542(A)	Si-NPN	=2N541:30V	2a	USA,Tix	BC168,BC183,BC238,BC548..
2N5420	Si-NPN	=2N5418:B>250	7c	-	BC337..338,BC635,BC637,BC639..
2N5421	Si-NPN	VHF-Dr/Out,36V,0,5A,Pq=1W(175MHz)	2a$	Itt,Sem,Tix	BFQ42,BFR98,BLW16,BLY61
2N5422	Si-NPN	VHF-Dr/Out,36V,1A,Pq=2W(175MHz)	2a$	Itt,Sem,Tix	BFQ43,2N6255
2N5423	Si-NPN	VHF-Pow,36V,2A,Pq=5W(175MHz)	49a*	Itt,Sem,Tix	BLW35,BLY79
2N5424(A)	Si-NPN	VHF-Pow,36V,4A,Pq=13W(175MHz)	49a*	Itt,Sem,Tix	BLW36
2N5425	Si-NPN-Darl	Sw,Pow,60V,5A,32,5W(Tc=70°),B>500	2a	Fch,Sca,Sem	-
2N5426	Si-NPN-Darl	=2N5425:B>1000	2a	-	-
2N5427	Si-NPN	=2N5336:7A,40W	22a$	USA,Mot,Sgs	MJE15028,2N6316,2N6372,2SC3254
2N5428	Si-NPN	=2N5337:7A,40W	22a$	USA,Mot,Sgs	MJE15028,2N6316,2N6372,2SC3254
2N5429	Si-NPN	=2N5338:7A,40W	22a$	USA,Mot,Sgs	MJE15028
2N543(A)	Si-NPN	=2N541:50V	2a	USA,Tix	BC167,BC182,BC237,BC547..
2N5430	Si-NPN	=2N5339:7A,40W	22a$	USA,Mot,Sgs	MJE15028
2N5431	UJT-P	Ip<0,4µA,Iv>2mA	2r$	Mot	-
2N5432	N-FET	Sw,25V,0,4A,Idss>150mA,Up<10V	2b&	USA,Tho,Tix	-
2N5433	N-FET	Sw,25V,0,4A,0.3W,7Ω,Idss>100mA,Up<9V	2b&	USA,Tho,Tix	-
2N5434	N-FET	Sw,25V,0,4A,Idss>30mA,Up<4V	2b&	USA,Tho,Tix	-
2N5435	Ge-PNP	AF,Sw-Pow,80V,60A,120W,B>20	23a$	Gpd,Mot	MP5435
2N5436	Ge-PNP	=2N5435:110V	23a$	-	MP5436
2N5437	Ge-PNP	=2N5435:140V	23a$	-	MP5437
2N5438	Ge-PNP	=2N5435:B>40	23a$	-	MP5438
2N5439	Ge-PNP	=2N5435:110V,B>40	23a$	-	MP5439
2N544	Ge-PNP	HF,18V,0,01A,0,08W,30MHz	1g	Rca,Syl	AF124..126,AF200
2N544/12,/33	Ge-PNP	=2N544:24V	5g	Syl	AF124..126,AF200
2N5440	Ge-PNP	=2N5435:140V,B>40	23a$	-	MP5440
2N5441	Triac	200V,40A,Igt/Ih<100/<60mA	29b$	Mot,Rca	T6400B
2N5442	Triac	=2N5441:400V	29b$	-	T6400D
2N5443	Triac	=2N5441:600V	29b$	-	T6400M
2N5444	Triac	=2N5441:	21b$	-	T6401B
2N5445	Triac	=2N5442:	21b$	-	T6401D
2N5446	Triac	=2N5443:	21b$	-	T6401M
2N5447	Si-PNP	GenP,40V,0,2A,0,3W,>100MHz	7a	USA,EUR,Mic	BC327,BC636,BC638,BC640..
2N5448	Si-PNP	GenP,50V,0,2A,0,3W,>100MHz	7a	-	BC327,BC636,BC638,BC640..
2N5449	Si-NPN	GenP,50V,0,8A,0,36W,>100MHz	7a	USA,EUR,Mic	BC337,BC635,BC637,BC639..
2N545	Si-NPN	AF,Sw,60V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5450	Si-NPN	GenP,50V,0,8A,0,36W,>100MHz	7a	-	BC337,BC635,BC637,BC639..
2N5451	Si-NPN	GenP,40V,0,8A,0,36W,>100MHz	7a	-	BC337,BC635,BC637,BC639..
2N5452	N-FET	Dual,LN,50V,Idss>0,5mA,Up<4,5V	81bx	Isi,Nsc,Six	BFQ10..16,2N3921..22,2N3954..59
2N5453	N-FET	Dual,LN,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N3921..22,2N3954..59
2N5454	N-FET	Dual,LN,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N3921..22,2N3954..59
2N5455	Si-PNP	Sw,15V,0,3A,0,34W,<30/40nS	2a$	Fch	BSX36
2N5456	Si-PNP	Sw,25V,0,3A,0,34W,<30/40nS	2a$	-	BSX36
2N5457	N-FET	GenP,sym,25V,Idss>1mA,Up<6V	7d	Isi,Mic,Mot	2SK246,2SK330
2N5458	N-FET	GenP,sym,25V,2.9mA,Idss>2mA,Up<7V	7d	-	BFS71,2N3822,2N4221,2N5361..
2N5459	N-FET	GenP,sym,25V,Idss>4mA,Up<8V	7d	-	BF244B..245B,BFS72,2N3823,2N4222,..
2N546	Si-NPN	AF,Sw,30V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5460	P-FET	GenP,LN,40V,Idss>1mA,Up<6V	7c	Isi,Mot,Nsc	2SJ103,2SJ105
2N5461	P-FET	GenP,LN,40V,9mA,0.31W,Idss>2mA,Up<7,5V	7c	-	BF320B
2N5462	P-FET	GenP,LN,40V,16mA,Idss>4mA,Up<9	7c	-	2N4360
2N5463	P-FET	=2N5460:60V	7c	-	-
2N5464	P-FET	=2N5461:60V	7c	-	-
2N5465	P-FET	=2N5462:60V	7c	-	-
2N5466	Si-NPN	Sw,Pow,500/400V,3A,140W,>2,5MHz	23a$	USA	BUX15,BUX45,BUX48A,2SC3041,2SD640..
2N5467	Si-NPN	=2N5466:700/400V	23a$	-	BUS11(A),BUX47(A),BUX48A,BUX82..83..
2N5468	Si-NPN	=2N5466:70W	22a$	-	BUT93,BUY63..64,MJ4380..81..
2N5469	Si-NPN	=2N5466:700/400V,70W	22a$	-	BUT11(A),BUV46(A),MJ4381,3SC3490..
2N547	Si-NPN	AF,Sw,60V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..

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2N5470	Si-NPN	UHF-A/Dr,55V,0,2A,Pq=2W(1GHz)	Koax	Rca	2N5920
2N5471	P-FET	GenP,sym,40V,Idss>0,02mA,Up<4V	5g+	Mot	2N5797
2N5472	P-FET	GenP,sym,40V,Idss>0,05mA,Up<4V	5g+	Mot	2N5797
2N5473	P-FET	GenP,sym,40V,Idss>0,1mA,Up<6V	5g+	Mot	2N5798
2N5474	P-FET	GenP,sym,40V,Idss>0,2mA,Up<7V	5g+	Mot	2N5798
2N5475	P-FET	GenP,sym,40V,Idss>0,4mA,Up<8V	5g+	Mot	BF320A,2N3909,2N3820,2N5799
2N5476	P-FET	GenP,sym,40V,Idss>0,8mA,Up<9V	5g+	Mot	2N5800
2N5477	Si-NPN	=2N5336:7A,60W	49a$	USA,Mot	2N5339
2N5478	Si-NPN	=2N5337:7A,60W	49a$	USA,Mot	2N5339
2N5479	Si-NPN	=2N5338:7A,60W	49a$	USA,Mot	2N5339
2N548	Si-NPN	AF,Sw,30V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5480	Si-NPN	=2N5339:7A,60W	49a$	USA,Mot	2N5339
2N5481	Si-NPN	UHF-Dr/Out,50V,0,2A,5W,3GHz	55r	Trw	BFQ68
2N5482	Si-NPN	UHF-Dr/Out,50V,0,35A,10W,3GHz	55r	Trw	BFQ68,BFQ136,BFT99
2N5483	Si-NPN	UHF-Dr/Out,45V,0,7A,20W,3GHz	55r	Trw	BFQ136
2N5484	N-FET	VHF/UHF,25V,5mA,0.31W,Idss>1mA,Up<3V	7d	USA,EUR,Mic	BF410A,B
2N5485	N-FET	VHF/UHF,25V,4mA,Idss>4mA,Up<4V	7d	-	BF256A,B
2N5486	N-FET	VHF/UHF,25V,Idss>8mA,Up<6V	7d	-	BF256B,C,2N5397
2N5487	Si-NPN	Sw,120V,5A,15W(Tc=25°),<125/450n5	2a$	USA,Trw	BUX34,BUY80,2N4895..97
2N5487-1	Si-NPN	Sw,120V,5A,1,2W,<125/450n5	2a$	-	BUX34,BUY80,2N4895..97
2N5487-3	Si-NPN	Sw,120V,5A,1,5W,<125/450n5	2a$o	-	BUX34,BUY80,2N4895..97
2N5488	Si-NPN	Sw,150V,5A,15W(Tc=25°),<125/550n	2a$	USA,Trw	BUY80,2N4897
2N5488-1	Si-NPN	Sw,150V,5A,1,2W,<125/550n	2a$	-	BUY80,2N4897
2N5488-3	Si-NPN	Sw,150V,5A,1,5W,<125/550n	2a$o	-	BUY80,2N4897
2N5489	Si-NPN	Sw,Pow,125/100V,40A,300W,>0,5MHz	49a$	USA	2N6309..11
2N549	Si-NPN	AF,Sw,60V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5490	Si-NPN	AF,Sw-Pow,60V,7A,50W,>0,8MHz	17j$	USA,Mot,Tho	BD243A,BD543A,BD797,BD807,MJE3055T...
2N5491	Si-NPN	=2N5490	17j$	-	BD243A,BD543A,BD797,BD807,MJE3055T...
2N5492	Si-NPN	AF,Sw-Pow,75V,7A,50W,>0,8MHz	17j$	-	BD243B,BD543B,BD707,BD799,BD809..
2N5493	Si-NPN	=2N5492	17j$	-	BD243B,BD543B,BD799,BD809..
2N5494	Si-NPN	AF,Sw-Pow,60W,7A,50W,>0,8MHz	17j$	-	BD243A,BD543A,BD707,BD797,BD807..
2N5495	Si-NPN	=2N5495	17j$	-	BD243A,BD543A,BD797,BD807,MJE3055T...
2N5496	Si-NPN	AF,Sw-Pow,90V,7A,50W,>0,8MHz	17j$	-	BD243B,BD543C,BD709,BD801,2SD550..
2N5497	Si-NPN	=2N5498	17j$	-	BD243B,BD543C,BD801,2SD550..
2N5498	Si-NPN	Sw,Pow,150/130V,15A,200W,>1MHz	23a$	Fairchild	BDX50,BUW57..58,BUX40,2N3773..
2N55	Ge-PNP	AF,45V,10mA,0,2W,0,5MHz	24e	Whs	ASY48,2SB56A
2N550	Si-NPN	AF,Sw,30V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5505	P-FET	Dual,LN,30V,Idss<7mA,Up<4V	81bx	Tsc	-
2N5506	P-FET	Dual,30V,Idss<7mA,Up<4V	81bx	-	-
2N5507	P-FET	Dual,30V,Idss<7mA,Up<4V	81bx	-	-
2N5508	P-FET	Dual,30V,Idss<7mA,Up<4V	81bx	-	-
2N5509	P-FET	Dual,30V,Idss<7mA,Up<5V	81bx	-	-
2N551	Si-NPN	AF,Sw,60V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5510	P-FET	Dual,30V,Idss<5mA,Up<4V	81bx	-	-
2N5511	P-FET	Dual,30V,Idss<5mA,Up<4V	81bx	-	-
2N5512	P-FET	Dual,30V,Idss<5mA,Up<4V	81bx	-	-
2N5513	P-FET	Dual,30V,Idss<5mA,Up<4V	81bx	-	-
2N5514	P-FET	Dual,30V,Idss<5mA,Up<5V	81bx	-	-
2N5515	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	Isi,Nsc,Six	BFQ10..16,2N5045..47,2N5452..54
2N5516	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5517	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5518	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5519	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N552	Si-NPN	AF,Sw,30V,0,8A,0,6W(Ta=100°),>4MHz	2a$	USA	BC140..141,BC300..302,2N3053..
2N5520	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5521	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5522	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5523	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5524	N-FET	Dual,LN,40V,Idss<0,5mA,Up<4V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5525	Si-NPN-Darl	GenP,40V,0,2A,0,36W,B>5000	7c	TI	BC517,BC617,BC875,MPSA25..26..
2N5526	Si-NPN-Darl	=2N5525:B>1000	7c	-	BC517,BC617,BC875,MPSA25..26..
2N5527	Si-NPN	Sw,Pow,RadH,60V,5A,5W(Tc=25°),>200MHz	2a$	Sol,Ssi,Stc	-
2N5528	Si-NPN	=2N5527:RadH,10A,35W	49a$	-	-
2N5529	Si-NPN	=2N5527:RadH,10A,35W	49a$	-	-

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2N553	Ge-PNP	AF,Sw-Pow,80V,Ueb=40V,4A,35W	23a$	USA	AL102..103,AUY21..22,2N1546..48..
2N5530	Si-NPN	=2N5527:RadH,10A,35W	49a	-	-
2N5531	Si-NPN	Sw,Pow,RadH,90V,5A,5W(Tc=25°),>200MHz	2a$	Sol,Ssi,Stc	-
2N5532	Si-NPN	=2N5531:RadH,10A,35W	49a$	-	-
2N5533	Si-NPN	=2N5531:RadH,10A,35W	49a$	-	-
2N5534	Si-NPN	=2N5531:RadH,10A,35W	49a	-	-
2N5535	Si-NPN	Sw,Pow,RadH,60V,20A,50W,>150MHz	49a$	Sol,Ssi,Stc	-
2N5536	Si-NPN	=2N5535:RadH	49a	-	-
2N5537	Si-NPN	=2N5535:RadH,90V	49a$	-	-
2N5538	Si-NPN	=2N5535:RadH,90V	49a	-	-
2N5539	Si-NPN	Sw,Pow,175V,20A,100W(Tc=100°),>20MHz	49a$	Sol,Ssi,Stc	2N2818,2N2822
2N554	Ge-PNP	AF,Sw-Pow,15V,Ueb=15V,3A,40W	23a$	USA,Mot	AD149,AUY19..20,2N2137..46..
2N5540	Si-NPN	Sw,Pow,325V,10A,50W(Tc=100°),>20MHz	49a$	Sol,Ssi,Stc	-
2N5541	Si-NPN	Sw,Pow,175V,5A,8,75W(Tc=100°),>20MHz	2a$	Sol,Ssi,Stc	BUY48..49
2N5542	Si-NPN	Sw,Pow,175V,10A,50W(Tc=100°),>20MHz	49a$	Sol,Ssi,Stc	-
2N5543	N-FET	Sw,300V,Idss>2mA,Up<15V	2b&	Tdy,Tix	2N4882
2N5544	N-FET	Sw,200V,Idss>2mA,Up<15V	2b&	Tdy,Tix	2N4883
2N5545	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	Nsc,Six,Sol	BFQ10..16,2N5045..47,2N5452..54
2N5546	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5547	N-FET	Dual,50V,Idss>0,5mA,Up<4,5V	81bx	-	BFQ10..16,2N5045..47,2N5452..54
2N5548	MOS-P-FET-e	Chopper,25V,Idss<10nA,Up<5V	7b	TI	-
2N5549	N-FET	VHF/Sw,40V,Idss>10mA,Up<6V	2b&	TI	BF256C,BF348,BFT10,2N5397,2N5486
2N555	Ge-PNP	=2N554:30V	23a$	USA,Mot	AD149,AUY19..20,2N2137..46..
2N5550	Si-NPN	Vid,160V,0,6A,0,625W,>100MHz	7e	USA,EUR,Tos	BF391..393,BFP22,MPSA42..43..
2N5550S	Si-NPN	-	35	Kec	→2N5550S
2N5551	Si-NPN	Vid,180V,0.6A,0.31W	7e	EUR,USA,Tos	BF391..393,BFP22,MPSA42..43..
2N5551C	Si-NPN	=2N5550:180V	7c	Kec	→2N5551
2N5551S	Si-NPN	-	35	Kec	→2N5551S
2N5552	Si-NPN	Sw,Pow,120V,10A,15W(Tc=25°),>30MHz	2a$	USA,Nsc,Trw	BUY82,(2SC2527)
2N5552-1	Si-NPN	=2N5552:	2a$	-	BUY82,(2SC2527)
2N5552-2(-4)	Si-NPN	=2N5552:	2a$o	-	BUY82,(2SC2527)
2N5555	N-FET	Sw,Sym,25V,Idss>15mA,Up<5V	7d	USA,Mot,Nsc	2N4092
2N5556	N-FET	GenP,LN,30V,Idss>0,5mA,Up<4V	5h+	USA,Mot,Nsc	BFS70,2N3821,2N4220,2SK104,2SK301
2N5557	N-FET	GenP,LN,30V,Idss>2mA,Up<5V	5h+	USA,Mot,Nsc	2SK107
2N5558	N-FET	GenP,LN,30V,Idss>4mA,Up<6V	5h+	USA,Mot,Nsc	BFS80,BFW11,2N4416,2N5362..
2N5559	Si-NPN	Sw,Pow,150/120V,10A,100W,>0,8MHz	23a$	Sol,Ssi,Tra	BD745E,BDX11,BUV50,2N3442,2SD1047
2N556	Ge-NPN	AF,Sw,25V,0,2A,0,1W,<3,5/2µS	2a	USA	AC127,ASY28..29,ASY73..75
2N5560	Si-NPN	Sw,Pow,175/120V,30A,150W,>40MHz	49a$	-	2N6324..25
2N5561	N-FET	Dual,LN,50V,Idss<10mA,Up<3V	81bx	Nsc,Sol,Tsc	-
2N5562	N-FET	Dual,LN,50V,Idss<10mA,Up<3V	81bx	-	-
2N5563	N-FET	Dual,LN,50V,Idss<10mA,Up<3V	81bx	-	-
2N5564	N-FET	Dual,LN,40V,Idss>5mA,Up<3V	81bx	Isi,Mic,Nsc	-
2N5565	N-FET	Dual,LN,40V,Idss>5mA,Up<3V	81bx	-	-
2N5566	N-FET	Dual,LN,40V,Idss>5mA,Up<3V	81bx	-	-
2N5567	Triac	200V,10A,Igt/Ih<40/<30mA	29b$	Mot,Rca	T4101B
2N5568	Triac	=2N5567:400V	29b$	-	T4101D
2N5569	Triac	=2N5567:	21b$	-	T4111B
2N557	Ge-NPN	AF,Sw,20V,0,2A,0,1W,<6,5/2,5µS	2a	USA	AC127,ASY28..29,ASY73..75
2N5570	Triac	=2N5568:	21b$	-	T4111D
2N5571	Triac	200V,15A,Igt/Ih<80/<75mA	29b$	Mot,Rca	2N6157,T6400B,2N5441
2N5572	Triac	=2N5571:400V	29b$	-	2N6158,T6400D,2N5442
2N5573	Triac	=2N5571:	21b$	-	T6411B,2N6160,T6410B,2N5444
2N5574	Triac	=2N5572:	21b$	-	T6411D,2N6161,T6410D,2N5445
2N5575	Si-NPN	Sw,Pow,70/50V,80A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N5576	Si-NPN	Sw,Pow,70/50V,80A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N5577	Si-NPN	Sw,Pow,70/50V,80A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N5578	Si-NPN	Sw,Pow,90/70V,60A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N5579	Si-NPN	Sw,Pow,90/70V,60A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N558	Ge-NPN	AF,Sw,15V,0,2A,0,1W,<3,5/2µS	2a	USA	AC127,ASY28..29,ASY73..75
2N5580	Si-NPN	Sw,Pow,90/70V,60A,300W,>0,4MHz	23a$	Rca,Stc,Tra	-
2N5581	Si-NPN	=2N2221A:0,5W	2a$	USA,Mot	→2N2221A
2N5582	Si-NPN	=2N2222A:0,5W	2a$	USA,Mot	→2N2222A
2N5583	Si-PNP	UHF-A/Dr,30V,0,5A,1W,>1300MHz	2a$	Mot	-
2N5584	Si-NPN	Sw,Pow,225/180V,30A,100W(Tc=100°),>70MHz	49a$	USA,Trw	(2N6324..25)

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2N5587	Si-NPN	Sw,Pow,120/120V,80A,300W,>0,5MHz	49a$	Sol,Ssi,Stc	2N6309..11
2N5588	Si-NPN	=2N5587:160/160V	49a$	-	-
2N5589	Si-NPN	VHF-Pow,36V,0,6A,Pq=3W(175MHz)	55r	Mot,Tho	BLY85,2N6080
2N559	Ge-PNP	Sw,15V,0,05A,0,15W,100/37nS	2a$	USA,Mot	ASZ21,2N705(A),2N2635,2N2955..57
2N5590	Si-NPN	VHF-Pow,36V,2A,Pq=10W(175MHz)	55r	Mot,Tho,Tix	BLW19,BLW37,MRF208,MRF212
2N5591	Si-NPN	VHF-Pow,36V,4A,Pq=25W(175MHz)	55r	-	BLY89,MRF209,MRF238,2N6082..83
2N5592	N-FET	GenP,50V,Idss>1mA,Up<5V	5h+	Sol	2N5360,2N5246,2SK107,2SK161
2N5593	N-FET	GenP,50V,Idss>1mA,Up<5V	5h+	Sol	2N5360,2N5246,2SK107,2SK161
2N5594	N-FET	GenP,50V,Idss>1mA,Up<5V	5h+	Sol	2N5360,2N5246,2SK107,2SK161
2N5595	Si-NPN	UHF-Pow,55V,1,2A,30W,>1500MHz	55r	Trw	-
2N5596	Si-NPN	UHF-Pow,55V,2,5A,45W,>1500MHz	55r	Trw	-
2N5597	Si-PNP	AF,Sw-Pow,80V,2A,20W,>60MHz	22a$	USA,Tix	2SA1078..1079,2SA1288
2N5598	Si-NPN	AF,Sw-Pow,80V,2A,20W,>60MHz	22a$	USA,Tix	2SC2528..2529,2SC3252
2N5599	Si-PNP	AF,Sw-Pow,100V,2A,20W,>50MHz	22a$	USA,Tix	2SA1078..1079
2N56	Ge-PNP	AF,45V,10mA,0,2W,0,5MHz	24e	Whs	ASY48,2SB56A
2N560	Si-NPN	AF,Sw,60V,0,1A,0,5W,<60/50nS	2a$	USA	2N3722..23,2N3725,2SC1385
2N5600	Si-NPN	AF,Sw-Pow,100V,2A,20W,>50MHz	22a$	USA,Tix	2SC2528..2529
2N5601	Si-PNP	AF,Sw-Pow,100V,2A,20W,>60MHz	22a$	USA,Tix	2SA1078..1079
2N5602	Si-NPN	AF,Sw-Pow,100V,2A,20W,>60MHz	22a$	USA,Tix	2SC2528..2529
2N5603	Si-PNP	AF,Sw-Pow,120V,2A,20W,>50MHz	22a$	USA,Tix	2SA1078..1079
2N5604	Si-NPN	AF,Sw-Pow,120V,2A,20W,>50MHz	22a$	USA,Tix	2SC2528..2529
2N5605	Si-PNP	AF,Sw-Pow,80V,5A,25W,>70MHz	22a$	USA,Tix	MJE15029,MJE15031,2SA1289
2N5606	Si-NPN	AF,Sw-Pow,80V,5A,25W,>70MHz	22a$	USA,Tix	MJE15028,ME15030,2SC3253
2N5607	Si-PNP	AF,Sw-Pow,100V,5A,25W,>60MHz	22a$	USA,Tix	MJE15029,MJE15031
2N5608	Si-NPN	AF,Sw-Pow,100V,5A,25W,>60MHz	22a$	USA,Tix	MJE15028,ME15030
2N5609	Si-PNP	AF,Sw-Pow,100V,5A,25W,>70MHz	22a$	USA,Tix	MJE15029,MJE15031
2N561	Ge-PNP	AF,Sw-Pow,80V,5A,50W	23a$	USA	AL102..103,AUY21..22,2N1546..48..
2N5610	Si-NPN	AF,Sw-Pow,100V,5A,25W,>70MHz	22a$	USA,Tix	MJE15028,ME15030
2N5611	Si-PNP	AF,Sw-Pow,120V,5A,25W,>60MHz	22a$	USA,Tix	MJE15029,MJE15031
2N5612	Si-NPN	AF,Sw-Pow,120V,5A,25W,>60MHz	22a$	USA,Tix	MJE15028,ME15030
2N5613	Si-PNP	AF,Sw-Pow,80V,5A,50W,>70MHz	23a$	USA	2N5621,2SA1141,2SA1146,2SA1186..
2N5614	Si-NPN	AF,Sw-Pow,80V,5A,50W,>70MHz	23a$	USA	2N5622,2SC2681,2SC2706,2SC2837,BDW51C...
2N5615	Si-PNP	AF,Sw-Pow,100V,5A,50W,>60MHz	23a$	USA	2N5623,2SA1141,2SA1146,2SA1186..
2N5616	Si-NPN	AF,Sw-Pow,100V,5A,50W,>60MHz	23a$	USA	2N5624,2SC2681,2SC2706,2SC2837,BDW51C...
2N5617	Si-PNP	AF,Sw-Pow,100V,5A,50W,>70MHz	23a$	USA	2N5625,2SA1141,2SA1146,2SA1186..
2N5618	Si-NPN	AF,Sw-Pow,100V,5A,50W,>70MHz	23a$	USA	2N5626,2SC2681,2SC2706,2SC2837,BDW51C...
2N5619	Si-PNP	AF,Sw-Pow,120V,5A,50W,>60MHz	23a$	USA	2N5627,2SA1141,2SA1146,2SA1186..
2N5620	Si-NPN	AF,Sw-Pow,120V,5A,50W,>60MHz	23a$	USA	2N5628,2SC2681,2SC2706,2SC2837..
2N5621	Si-PNP	AF,Sw-Pow,80V,10A,100W,>40MHz	23a$	USA	2SA1146,2SA1186,2SA1227,2SSA1386
2N5622	Si-NPN	AF,Sw-Pow,80V,10A,100W,>40MHz	23a$	USA	2SC2681,2SC2706,2SC2837,2SSC2987
2N5623	Si-PNP	AF,Sw-Pow,100V,10A,100W,>30MHz	23a$	USA	2SA1146,2SA1186,2SA1227,2SSA1386
2N5624	Si-NPN	AF,Sw-Pow,100V,10A,100W,>30MHz	23a$	USA	2SC2681,2SC2706,2SC2837,2SSC2987
2N5625	Si-PNP	AF,Sw-Pow,100V,10A,100W,>40MHz	23a$	USA	2SA1146,2SA1186,2SA1227,2SSA1386
2N5626	Si-NPN	AF,Sw-Pow,100V,10A,100W,>40MHz	23a$	USA	2SC2681,2SC2706,2SC2837,2SSC2987
2N5627	Si-PNP	AF,Sw-Pow,120V,10A,100W,>30MHz	23a$	USA	2SA1146,2SA1186,2SA1227,2SSA1386
2N5628	Si-NPN	AF,Sw-Pow,120V,10A,100W,>30MHz	23a$	USA	2SC2681,2SC2706,2SC2837,2SSC2987
2N5629	Si-NPN	AF,Sw-Pow,100V,16A,200W,>1MHz	23a$	Mot,Rca	BD317,BDX50,2N3773,2SC2608
2N563	Ge-PNP	AF,Sw,30V,0,3A,0,15W,B=25,0,8MHz	1a&	USA	AC128,AC152..153,AC188
2N5630	Si-NPN	=2N5629:120V	23a$	-	BDX50,2N3773,MJ15015,2SC2608
2N5631	Si-NPN	=2N5629:140V	23a$	-	BDX50,2N3773,MJ15015,2SC2608
2N5632	Si-NPN	AF,Sw-Pow,100V,10A,150W,>1MHz	23a$	USA,Mot,Rca	BD317,BDX50,2N3773,2SC2608
2N5633	Si-NPN	=2N5632:120V	23a$	-	BDX50,BUV50,2N3773,MJ15015,2SC2608
2N5634	Si-NPN	=2N5632:140V	23a$	-	BDX50,BUV50,MJ15015,2N3773,2SC2608
2N5635	Si-NPN	UHF-Pow,60V,1A,Pq=3,2W(400MHz)	55r	Mot,Tho	BLW93
2N5636	Si-NPN	UHF-Pow,60V,1,5A,Pq=8,4W(400MHz)	55r	Mot,Tho	BLW91,2SC2893
2N5637	Si-NPN	UHF-Pow,60V,3A,Pq=22W(400MHz)	55r	Mot,Tho	BLX95,2SC2894
2N5638	N-FET	Sw,Chopper,30V,Idss>50mA,<9/15nS	7d	USA,Mot,Mic	BFS74,BFS77,BSV78,2N4856,2N4859..
2N5639	N-FET	Sw,Chopper,30V,10mA,310mW,Idss>25mA,<14/30nS	7d	USA,Mot,Mic	BFS75,BFS78,BSV79,2N4857,2N4860..
2N564	Ge-PNP	=2N563:0,12W	2a	USA	AC128,AC152..153,AC188
2N5640	N-FET	Sw,Chopper,30V,Idss>5mA,<18/45nS	7d	USA,Mot,Mic	BFS76,BFS79,BSV80,2N4858,2N4861..
2N5641	Si-NPN	VHF-Pow,65V,1A,Pq=7W(175MHz)	55r	Mot,Tho,Tix	BLY98
2N5642	Si-NPN	VHF-Pow,65V,3A,Pq=20W(175MHz)	55r	Mot,Tho,Tix	2SC2888
2N5643	Si-NPN	VHF-Pow,65V,5A,Pq=40W(175MHz)	55r	Mot,Tho,Tix	BLW25,2SC2889
2N5644	Si-NPN	UHF-Dr/Out,36V,0,25A,Pq=1W(470MHz)	55r	Mot,Tix	2N5944

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2N5645	Si-NPN	UHF-Dr/Out,36V,1A,Pq=4W(470MHz)	55r	Mot,Tix	BLW43,BLW80
2N5646	Si-NPN	UHF-Dr/Out,36V,2A,Pq=12W(470MHz)	55r	Mot,Tix	BLW44,2N5946
2N5647	N-FET	GenP,LN,50V,Idss>0,3mA,Up<1,8V	5h+	Sol	2N4338,2SK118
2N5648	N-FET	GenP,LN,50V,Idss>0,5mA,Up<2,4V	5h+	Sol	2N4339,2N5358,2SK83,2SK193..195
2N5649	N-FET	GenP,LN,50V,Idss>0,8mA,Up<3V	5h+	Sol	2N4339,2N5358,2SK83,2SK193..195
2N565	Ge-PNP	AF,Sw,30V,0,3A,0,15W,B=55,1MHz	1a&	USA	AC128,AC152..153,AC188
2N5650	Si-NPN	UHF,20V,0,03A,0,15W,>2GHz	5g	Nec,Six	BFR15,BFS55,BFT66..67
2N5651	Si-NPN	UHF,20V,0,03A,0,15W,>2GHz	5g	Nec,Six	BFR15,BFS55,BFT66..67
2N5652	Si-NPN	UHF,20V,0,03A,0,15W,>2GHz	5g	-	BFR15,BFS55,BFT66..67
2N5653	N-FET	Sw,Chopper,Idss>40mA,<9/15nS	7d	USA,Mot,Mic	BFS74,BFS77,BSV78,2N4856,2N4859
2N5654	N-FET	Sw,Chopper,Idss>15mA,<14/30nS	7d	USA,Mot,Mic	BFS75,BFS78,BSV79,2N4857,2N4860
2N5655	Si-NPN	AF,Sw-Vid-Pow,275V,0,5A,20W,>10MHz	14h$	Mot,Nsc,Sgs	BF668,BF758..759,MJE340
2N5656	Si-NPN	=2N5655:325V	14h$	-	BF759,MJE3440
2N5657	Si-NPN	=2N5655:375V	14h$	-	BD410,MJE3440,2SC2899,2SC3051,2SC3425
2N5658	Si-NPN	Sw,Pow,120/80V,10A,30W,>30MHz	49a$	USA	(2N5288..89,2N5542)
2N5659	Si-NPN	=2N5659:Iso	49a	-	(2N5288..89,2N5542)
2N566	Ge-PNP	=2N565:0,12W	2a	USA	AC128,AC152..153,AC188
2N5660	Si-NPN	AF,Sw-Pow,250/200V,1A,35W,>20MHz	22a$	USA	BUW40(A,B),TIP47..50,2N3738..39..
2N5661	Si-NPN	=2N5660:400/300V	22a$	-	BUW40(A,B),TIP47..50,2N4298..99..
2N5662	Si-NPN	=2N5660:15W(Tc=100°)	2a$	-	BSS48..49,BUX51..54,2N3439..40
2N5663	Si-NPN	=2N5660:400/300V,15W(Tc=100°)	2a$	-	BSS49,BUX54,2N3439
2N5664	Si-NPN	AF,Sw-Pow,250/200V,3A,52,5W,>20MHz	22a$	USA,Tix	BUY63..64,TIP75(A..C),2SC2929..
2N5665	Si-NPN	=2N5664:400/300V	22a$	-	BUY63..64,TIP75A..C,2SC2929..
2N5666	Si-NPN	=2N5664:15W(Tc=100°)	2a$	-	BUX51..54,2SD625
2N5667	Si-NPN	=2N5664:400/300V,15W(Tc=100°)	2a$	-	BUX54
2N5668	N-FET	VHF,25V,Idss>1mA,Up<4V	7d	Mic,Mot,Nsc	2N5246,2SK107,2SK161
2N5669	N-FET	VHF,25V,Idss>4mA,Up<6V	7d	Mic,Mot,Nsc	BFS80,BFW11,2N4416,2N5245,2N5398
2N567	Ge-PNP	AF,Sw,30V,0,3A,0,15W,B=100,1,5MHz	1a&	USA	AC128,AC152..153,AC188
2N5670	N-FET	VHF,25V,Idss>8mA,Up<8V	7d	Mic,Mot,Nsc	BF244C..245C,BFW10
2N5671	Si-NPN	AF,Sw-Pow,120/90V,30A,140W,>50MHz	23a$	USA,Sgs,Tix	BUV50
2N5672	Si-NPN	150/120V,30A,140W,0.5µS	23a$	-	BUV50
2N5675	Si-PNP	AF,Sw,125/100V,2A,1W,>50MHz	2a$	Ssi,Stc,Tra	-
2N5676	Si-PNP	=2N5675:...	22a$	-	2SA1078..79,2SA1133,2SB719..720
2N5677	Si-PNP	Sw,Pow,125/100V,10A,50W(Tc=100°)	49a$	USA	2N5290..91
2N5678	Si-PNP	Sw,Pow,125/100V,20A,100W(Tc=100°)	49a$	-	-
2N5679	Si-PNP	AF,Sw,100V,1A,1W,>30MHz	2a$	USA,Mot,Sgs	BCX60,BSS17,2N3634..35,2N5322
2N568	Ge-PNP	=2N567:0,12W	2a	USA	AC128,AC152..153,AC188
2N5680	Si-PNP	120V,1A,1W	2a$	-	2N3634..35
2N5681	Si-NPN	AF,Sw,100V,1A,1W,>30MHz	2a$	USA,Mot,Sgs	BCX40,2N3019..20,2N4300,2SC1860
2N5682	Si-NPN	=2N5681:120V	2a$	-	2N3019..20,2SC1860
2N5683	Si-PNP	AF,Sw-Pow,60V,50A,300W,>2MHz	23a$	USA,Mot,Tix	2N6377..79
2N5684	Si-PNP	=2N5683:80V	23a$	-	2N6377..79
2N5685	Si-NPN	AF,Sw-Pow,60V,50A,300W,>2MHz	23a$	USA,Mot,Tix	2N5575..80
2N5686	Si-NPN	=2N5685:80V	23a$	-	2N5578..80
2N5687	Si-NPN	HF-Dr/Out,40V,0,5A,5W(Tc=25°)	2a$	Tix,Trw	-
2N5688	Si-NPN	HF-Pow,40V,0,5A,10W	55r	Tix,Trw	-
2N5689	Si-NPN	HF-Pow,60V,3A,25W	55r	Tix,Trw	-
2N569	Ge-PNP	AF,Sw,30V,0,3A,0,15W,B=150,2MHz	1a&	USA	AC128,AC152..153,AC188
2N5690	Si-NPN	HF-Pow,50V,5A,50W	55r	Tix,Trw	-
2N5691	Si-NPN	HF-Pow,50V,8A,88W	59r	Tix,Trw	-
2N5692	Ge-PNP	Sw,Pow,50V,40A,120W	23a$	Gpd,Mot	2N2357..59,2N5435..40
2N5693	Ge-PNP	=2N5692:80V	23a$	-	2N2358..59,2N5435..40
2N5694	Ge-PNP	=2N5692:100V	23a$	-	2N2358..59,2N5436..37,2N5439..40
2N5695	Ge-PNP	=2N5692:120V	23a$	-	2N2359,2N5437,2N5440
2N5696	Ge-PNP	=2N5692:140V	23a$	-	2N5437,2N5440
2N5697	Si-NPN	HF-Dr/Out,40V,0,5A,3,5W(Tc=25°)	2a$	Tix,Trw	-
2N5698	Si-NPN	HF-Dr/Out,40V,0,5A,5W	51r	Tix,Trw	-
2N5699	Si-NPN	HF-Pow,40V,1A,10W	55r	Tix,Trw	-
2N57	Ge-PNP	AF,Sw-Pow,60V,0,8A,20W	-	Sol	-
2N570	Ge-PNP	=2N569:0,12W	2a	USA	AC128,AC152..153,AC188
2N5700	Si-NPN	HF-Pow,40V,3A,35W	55r	Trw	-
2N5701	Si-NPN	HF-Pow,40V,3A,35W	55r	Trw	-
2N5702	Si-NPN	HF-Dr/Out,36V,0,5A,0,88W	2a$	Tix,Trw	-
2N5703	Si-NPN	HF-Dr/Out,36V,0,75A,10W	55r	Tix,Trw	-

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2N5704	Si-NPN	HF-Pow,36V,2A,25W	55r	Tix,Trw	-
2N5705	Si-NPN	HF-Pow,36V,4A,44W	55r	Tix,Trw	-
2N5706	Si-NPN	HF-Pow,36V,7A,80W	59r	Tix,Trw	-
2N5707	Si-NPN	HF-Pow,70V,4A,Pq>20W(30MHz)	55r	Tix,Trw	MRF401,MRF449A
2N5708	Si-NPN	HF-Pow,70V,6A,Pq>20W(28MHz)	55r	Tix,Trw	MRF449A
2N5709	Si-NPN	HF-Pow,70V,12A,Pq>40W(28MHz)	59r	Tix,Trw	2SC1764
2N571	Ge-PNP	AF,Sw,30V,0,3A,0,15W,B=200,3MHz	1a&	USA	AC128,AC152..153,AC188
2N5710	Si-NPN	HF-Dr/Out,40V,0,5A,3,5W(Tc=25°)	2a$	Tix,Trw	-
2N5711	Si-NPN	HF-Dr/Out,60V,0,75A,10W	55r	Tix,Trw	-
2N5712	Si-NPN	HF-Pow,60V,2A,25W	55r	Tix,Trw	-
2N5713	Si-NPN	HF-Pow,60V,5A,45W	55r	Tix,Trw	-
2N5714	Si-NPN	HF-Pow,60V,8A,70W	60c	Trw	-
2N5715	Si-NPN	UHF-A/Dr,50V,0,2A,6W(Tc=25°),>3,5GHz	2a$	Trw	-
2N5716	N-FET	AF,LN,40V,Idss>0,05mA,Up<3V	7d	Mic,Mot,Nsc	2N3367,2N3370,2N4118
2N5717	N-FET	AF,LN,40V,Idss>0,2mA,Up<5V	7d	Mic,Mot,Nsc	2N3366,2N4119
2N5718	N-FET	AF,LN,40V,Idss>0,8mA,Up<8V	7d	Mic,Mot,Nsc	2N3365
2N5719	Thy-50Hz	60V,0,2A(Tc=90°),Igt/Ih<0,02/<2mA	2a$	Tag,Uni	(2N2324A)
2N572	Ge-PNP	=2N571:0,12W	2a	USA	AC128,AC152..153,AC188
2N5720	Thy-50Hz	=2N5719:100V	2a$	-	(2N2324A)
2N5721	Thy-50Hz	=2N5719:200V	2a$	-	(2N2326A)
2N5722	Thy-50Hz	=2N5719:300V	2a$	-	(2N2328A)
2N5723	Thy-50Hz	=2N5719:400V	2a$	-	(2N2329A)
2N5724	Thy-50Hz	=2N5719:0,39A(Tc=90°)	2a$	-	(2N2324A)
2N5725	Thy-50Hz	=2N5720:0,39A(Tc=90°)	2a$	-	(2N2324A)
2N5726	Thy-50Hz	=2N5721:0,39A(Tc=90°)	2a$	-	(2N2326A)
2N5727	Thy-50Hz	=2N5722:0,39A(Tc=90°)	2a$	-	(2N2328A)
2N5728	Thy-50Hz	=2N5723:0,39A(Tc=90°)	2a$	-	(2N2329A)
2N5729	Si-NPN	Sw,Pow,100/80V,5A,11,7W(Tc=25°),>30MHz	2a$	Sol,Ssi,Stc	2N489S..97,2N5338..39,BUX34,BUY80
2N573	Ge-PNP	AF,Sw,40V,0,25A,0,2W	2a	USA	2N1191..94,2SB56A
2N5730	Si-NPN	Sw,Pow,100/80V,10A,45W,>30MHz	49a	-	(2N5288..89)
2N5731	Si-NPN	Sw,Pow,100/80V,20A,75W,>30MHz	49a	Sol,Ssi,Stc	-
2N5732	Si-NPN	Sw,Pow,100/80V,20A,87,5W,>30MHz	23a$	-	(BDX40,BDY57,2N3772)
2N5733	Si-NPN	Sw,Pow,100/80V,30A,150W,>30MHz	49a	Sol,Ssi,Stc	-
2N5734	Si-NPN	Sw,Pow,100/80V,30A,125W,>30MHz	23a$	-	BUX10
2N5737	Si-PNP	AF,Sw-Pow,60V,10A,50W(Tc=100°),>10MHz	23a$	USA	BD312,BD546A,BDW22A,2N5875..76..
2N5738	Si-PNP	=2N5737:100V	23a$	-	BD318,BD546C,BDW22C,BDW52C,2N6229..31..
2N5739	Si-PNP	=2N5737:20W(Tc=100°)	22a$	-	BD708,BD744A,BD808,BDT82..
2N574	Ge-PNP	AF,Sw-Pow,60V,Ueb=28V,10A,187W	?49a$	Gpd,Sem	-
2N5740	Si-PNP	=2N5737:100V,20W(Tc=100°)	22a$	-	BD712,BD744C,BDT86,BDW52C...
2N5741	Si-PNP	AF,Sw-Pow,60V,20A,65W(Tc=100°),>10MHz	23a$	USA	BD250A,BD367,BD746A,2N5883..84..
2N5742	Si-PNP	=2N5741:100V	23a$	-	BD250C,BD746C,MJ4502
2N5743	Si-PNP	=2N5741:25W(Tc=100°)	22a$	-	2N5884
2N5744	Si-PNP	=2N5741:100V,25W(Tc=100°)	22a$	-	MJ4502
2N5745	Si-PNP	AF,Sw-Pow,80V,20A,200W,>2MHz	23a$	USA,Mot,Sgs	BD369,MJ4502,2N5884
2N574A	Ge-PNP	=2N574:80V	?49a$	-	-
2N575	Ge-PNP	AF,Sw-Pow,60V,Ueb=28V,25A,187W	?49a$	Gpd,Sem	-
2N5754	Triac	=T2303A	2a$	Rca,Tag	→T2303A
2N5755	Triac	=T2303B	2a$	-	→T2303B
2N5756	Triac	=T2303D	2a$	-	→T2303D
2N5757	Triac	=T2303M	2a$	-	→T2303M
2N5758	Si-NPN	AF,Sw-Pow,100V,6A,150W,>1MHz	23a$	USA,Mot,TixBD245C,BDV95,BDW51C,BDX95,2N5632..33..	
2N5759	Si-NPN	=2N5758:120V	23a$	-	BD245D,2N4348,2N5634,2SC2607..08..
2N575A	Ge-PNP	=2N575:80V	?49a$	-	-
2N576	Ge-NPN	AF,Sw,20V,Ueb=15V,0,4A,0,2W,5MHz	2a&	USA	-
2N5760	Si-NPN	=2N5758:140V	23a$	-	BD245D,2N4348,2N5634,2SC2607..08..
2N5761	Si-NPN	UHF,20V,0,03A,0,25W,>3,7GHz	51s	Nec	BFQ60,BFQ71,2SC1119,2SC1336..
2N5762	Si-NPN	UHF,20V,0,04A,0,3W,>3,3GHz	51s	Nec	BFQ60,BFQ71,2SC1119,2SC1336..
2N5763	Si-PNP	Sw,RadH,65V,0,6A,0,4W,<50/250nS	2a$	Mot	-
2N5764	Si-NPN	HF-Dr/Out,55V,0,75A,10W	55r	Trw	-
2N5765	Si-NPN	HF-Pow,55V,1,5A,19W	55r	Trw	-
2N5766	Si-NPN	HF-Dr/Out,55V,0,2A,5W	55r	Trw	-
2N5767	Si-NPN	HF-Dr/Out,55V,0,35A,10W	55r	Trw	-
2N5768	Si-NPN	HF-Dr/Out,55V,0,7A,20W	55r	Trw	-
2N5769	Si-NPN	Sw,40V,0,2A,0,625W,>500MHz,<12/18nS	7e	USA,Mic,Nsc	BSS10..11,BSX19..20,2N2368..69(A),..

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2N576A	Ge-NPN	=2N576: 40V, 8MHz	2a&	-	-
2N577	Opto	-		-	-
2N5770	Si-NPN	UHF, 30V, 0,05A, 0,7W, >900MHz	7e	USA,Nsc	BF377..378, BF689, BF763, 2N2857..
2N5771	Si-PNP	Sw, 15V, 0,05A, 0,625W, >850MHz, <15/20nS	7e	USA,Mot,Nsc	BSX36, 2N4313, 2N5056..57
2N5772	Si-NPN	Sw, 40V, 0,2A, 0,625W, >350MHz, <25/35nS	7e	USA,Min,Nsc	BSS10..11, BSX19..20, 2N2368..69(A),..
2N5773	Si-NPN	HF-Dr/Out, 65V, 0,5A, 5W	55r	Trw	-
2N5774	Si-NPN	HF-Pow, 65V, 1,5A, 18W	55r	Trw	-
2N5775	Si-NPN	HF-Pow, 65V, 3A, 40W	60c	Trw	-
2N5776	Si-NPN	HF-Pow, 65V, 6A, 70W	60c	Trw	-
2N5777..5780	Opto	-		-	-
2N578	Ge-PNP	AF, Sw, 20V, Ueb=12V, 0,4A, 0,12W, 5MHz	2a	USA	ASY76..77
2N5781	Si-PNP	AF, Sw, 80V, 3,5A, 1W, <500/2500nS	2a$	USA,Rca	2N4236, 2N6303, BSS44
2N5782	Si-PNP	=2N5781: 65V	2a$	-	2N3720, 2N3868, 2N4235..36, 2N6303, BSS44
2N5783	Si-PNP	=2N5781: 45V	2a$	-	2N3720, 2N3868, 2N4235..36, 2N6303, BSS44
2N5784	Si-NPN	AF, Sw, 80V, 3,5A, 1W, <5/15µS	2a$	USA,Rca	BSX63..64, 2N4238..39, 2N5339, 2SC2214..
2N5785	Si-NPN	=2N5784: 65V	2a$	-	BSX62..64, 2N4238..39, 2N5339, 2SC2214..
2N5786	Si-NPN	=2N5784: 45V	2a$	-	BSX62..64, 2N4237..39, 2SC2214..
2N5787	Thy-50Hz	30V, 0,24A, Igt/Ih<0,35/<10mA	8a$	Fch,Mot	(2N2323, 2N6332, TAG615-100, TIC44,)..
2N5788	Thy-50Hz	=2N5787: 60V	8a	-	(2N2324, 2N6334, TAG615-100, TIC46,)..
2N5789	Thy-50Hz	=2N5787: 100V	8a	-	(2N2324, 2N6334, TAG615-100, TIC46,)..
2N579	Ge-PNP	=2N578: 8MHz	2a	USA	ASY76..77
2N5790	Thy-50Hz	=2N5787: 200V	8a	-	(2N2326, 2N6335, TAG615-200, TIC47,)..
2N5791	Thy-50Hz	=2N5787: 300V	8a	-	(2N2328, 2N6336, TAG615-300, TAG06C,)+
2N5792	Thy-50Hz	=2N5787: 400V	8a	-	(2N2329, 2N6337, TAG615-400, TAG06D,)+
2N5793	Si-NPN	Dual, Sw, 75V, 0,6A, 0,6W, >250MHz	81bs	Mot,Ray,Sca	2N3409..11, 2N3728..29
2N5794	Si-NPN	Dual, Sw, 75V, 0,6A, 0,6W, >250MHz	81bs	-	2N3409..11, 2N3728..29
2N5795	Si-PNP	Dual, Sw, 60V, 0,6A, 0,6W, >200MHz	81bs	Mot,Ray,Sca	BFX11, 2N4015..16
2N5796	Si-PNP	Dual, Sw, 60V, 0,6A, 0,6W, >200MHz	81bs	-	BFX11, 2N4015..16
2N5797	P-FET	AF, Sym, 40V, Idss>0,02mA, Up<4V	7c	Mot	2N2606
2N5798	P-FET	AF, Sym, 40V, Idss>0,08mA, Up<6V	7c	Mot	-
2N5799	P-FET	AF, Sym, 40V, Idss>0,25mA, Up<8V	7c	Mot	-
2N580	Ge-PNP	=2N578: 15MHz	2a	USA	ASY76..77
2N5800	P-FET	AF, Sym, 40V, Idss>0,7mA, Up<9V	7c	Mot	-
2N5801	N-FET	GenP, LN, 40V, Idss>2mA, Up<4V	2b&	Mot	2N5360, 2N5246, 2SK107
2N5802	N-FET	GenP, LN, 40V, Idss>10mA, Up<6V	2b&	Mot	BF256C, BF348, BFT10, 2N5397, 2N5486
2N5803	N-FET	GenP, LN, 40V, Idss>30mA, Up<8V	2b&	Mot	BFT10C, 2SK125
2N5804	Si-NPN	Sw, Pow, 300/225, 5A, 110W, >15MHz	23a$	RCA	BUW71, BUX16A..C, BUX18(A..C)..
2N5805	Si-NPN	=2N5804: 375/300V	23a$	-	BUW71, BUX16B..C, BUX18B..C..
2N5806	Triac	200V, 25A, Igt/Ih<150/<75mA	21b$	Rca	BTX94/200
2N5807	Triac	=2N5806: 400V	21b$	-	BTX94/400
2N5808	Triac	=2N5806: 500V	21b$	-	BTX94/500
2N5809	Triac	=2N5806: 600V	21b$	-	BTX94/600
2N581	Ge-PNP	AF, Sw, 18V, 0,1A, 0,08W, 8MHz	2a	USA	ASY26..27, ASY76..77
2N5810	Si-NPN	AF-Driver, 35V, 0,75A, 0,5W, >100MHz, B>60	7a	Gen,Mic,Sem	BC337..338, BC635, BC637, BC639..
2N5811	Si-PNP	AF-Driver, 35V, 0,75A, 0,5W, >100MHz, B>60	7a	Gen,Mic,Sem	BC327..328, BC636, BC638, BC640..
2N5812	Si-NPN	=2N5810: >135MHz, B>150	7a	-	BC337..338, BC635, BC637, BC639..
2N5813	Si-PNP	=2N5811: >135MHz, B>150	7a	-	BC327..328, BC636, BC638, BC640..
2N5814	Si-NPN	=2N5810: 50V	7a	-	BC337, BC635, BC637, BC639..
2N5815	Si-PNP	=2N5811: 50V	7a	-	BC327, BC636, BC638, BC640..
2N5816	Si-NPN	=2N5810: 50V, >120MHz, B>100	7a	-	BC337, BC635, BC637, BC639..
2N5817	Si-PNP	=2N5811: 50V, >120MHz, B>100	7a	-	BC327, BC636, BC638, BC640..
2N5818	Si-NPN	=2N5810: 50V, >135MHz, B>150	7a	-	BC337, BC635, BC637, BC639..
2N5819	Si-PNP	=2N5811: 50V, >135MHz, B>150	7a	-	BC327, BC636, BC638, BC640..
2N582	Ge-PNP	AF, Sw, 25V, 0,1A, 0,12W, 18MHz	2a	USA	ASY26..27, ASY76..77
2N5820	Si-NPN	=2N5810: 70V	7a	-	BC639, 2SD667, 2SD1226, 2SD1768..
2N5821	Si-PNP	=2N5811: 70V	7a	-	BC640, 2B647, 2SB910, 2SB1041..
2N5822	Si-NPN	=2N5810: 70V, >120MHz, B>100	7a	-	BC639, 2SD667, 2SD1226, 2SD1768..
2N5823	Si-PNP	=2N5811: 70V, >120MHz, B>100	7a	-	BC640, 2B647, 2SB910, 2SB1041..
2N5824	Si-NPN	GenP, 50V, 0,1A, 0,36W, >90MHz, B>60	7a	USA,Gen,Mic	BC167, BC182, BC237, BCS47..
2N5825	Si-NPN	=2N5824: B>100	7a	-	BC167, BC182, BC237, BCS47..
2N5826	Si-NPN	=2N5824: B>150	7a	-	BC167, BC182, BC237, BCS47..
2N5827	Si-NPN	=2N5824: B>250	7a	-	BC167, BC182, BC237, BCS47..
2N5827A	Si-NPN	=2N5827: ra	7a	-	BC414, BCS50, 2SC1775(A), 2SC2390..
2N5828	Si-NPN	=2N5824: B>400	7a	-	BC167, BC182, BC237, BCS47..

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2N5828A	Si-NPN	=2N5828:ra	7a	-	BC414,BC550,2SC1775(A),2SC2390..
2N5829	Si-PNP	UHF,LN,30V,0,03A,0,2W,1,5GHz	5g	Mot,Sca,Tho	BF316,BF439,BF516,BF606,BFR38..
2N583	Ge-PNP	AF,Sw,18V,0,1A,0,08W,8MHz	2a	USA	ASY26..27,ASY76..77
2N5830	Si-NPN	Sw,Vid,120V,0,6A,0,625W,>100MHz	7e	Fch,Nsc,Spr	BF391..393,BFP22,MPSA42..43
2N5831	Si-NPN	=2N5830:160V	7e	-	BF391..393,BFP22,MPSA42..43
2N5832	Si-NPN	=2N5830:160V	7e	-	BF391..393,BFP22,MPSA42..43
2N5833	Si-NPN	=2N5830:200V	7e	-	BF391..393,BFP22,MPSA42..43
2N5834	Si-PNP	VHF-Dr/Out,60V,1A,Pq=2,5W(175MHz)	2	Mot,Tix	-
2N5835	Si-NPN	Fast-Sw,UHF,15V,15mA,0,2W,>2,5GHz	5g	Mot,Sca	BFR15,BFW99,BFT66..67
2N5836	Si-NPN	Fast-Sw,UHF,15V,0,2A,>2GHz	2a$	Mot,Sca	(BFR95)
2N5837	Si-NPN	Fast-Sw,UHF,10V,0,3A,>1,7GHz	2a$	Mot,Sca	(2SC1253,2SC1366,2SC1952)
2N5838	Si-NPN	Sw,Pow,275/250V,3A,100W,>5MHz	23a$	USA,Mot,Tix	BU606..608,BUX16A..C,BUW71..
2N5839	Si-NPN	=2N5838:300/275V	23a$	-	BU606..608,BUX16B..C,BUW71..
2N584	Ge-PNP	AF,Sw,25V,Ueb=12V,0,1A,0,12W,18MHz	2a	USA	ASY26..27,ASY76..77
2N5840	Si-NPN	=2N5838:375/350V	23a$	-	BU606..608,BUX16B..C,BUW71..
2N5841	Si-NPN	Fast-Sw,UHF,20V,0,1A,0,35W,>2,7GHz	5g	Mot,Sca	2SC3337,(BFR95)
2N5842	Si-NPN	Fast-Sw,UHF,20V,0,1A,0,35W,>2GHz	5g	-	2SC3337,(BFR95)
2N5843	Si-PNP	Dual,LN,50V,0,05A,0,6W,>200MHz	81bs	Fch,Mot	BFX11,2N4015..16
2N5844	Si-PNP	Dual,LN,50V,0,05A,0,6W,>250MHz	81bs	-	BFX11,2N4015..16
2N5845	Si-NPN	Sw,50V,1A,0,625W,<45/70nS	7e	Mot,Spr	2N3736..37,2N4013..14
2N5845A	Si-NPN	=2N5845:<40/65nS	7e	-	2N3736..37,2N4013..14
2N5846	Si-NPN	HF-Pow,36V,1A,Pq>3,5W(50MHz)	49a$	Mot	-
2N5847	Si-NPN	HF-Pow,36V,2A,Pq>8W(50MHz)	55r	Mot	-
2N5848	Si-NPN	HF-Pow,48V,3,5A,Pq>20W(50MHz)	55r	Mot	MRF234
2N5849	Si-NPN	HF-Pow,48V,7A,Pq>40W(50MHz)	55r	Mot,Tho	-
2N585	Ge-NPN	AF,Sw,25V,Ueb=20V,0,2A,0,12W,5MHz	2a	USA	ASY28..29,ASY73..75
2N5851	Si-NPN	Fast-Sw,UHF,30V,0,1A,0,5W,1,6/1,6nS	5g	Mot,Sca,Ssi	-
2N5852	Si-NPN	Fast-Sw,UHF,30V,0,1A,0,5W,1,6/1,6nS	5g	Mot,Sca,Ssi	-
2N5853	Si-PNP	Sw,Pow,100V,10A,66W(Tc=100°),>15MHz	49a	USA	2N5290..91
2N5854	Si-NPN	Sw,Pow,100V,10A,66W(Tc=100°),>20MHz	49a	-	2N5288..89
2N5855	Si-PNP	GenP,60V,1A,0,75W,>100MHz	8a	Fch	BC327A,BC638,BC640,2SB647..
2N5856	Si-NPN	GenP,60V,1A,0,75W,>100MHz	8a	Fch	BC337A,BC637,BC639,2SB647..
2N5857	Si-PNP	=2N5855:80V	8a	-	BC640,2SB647,2SB910,2SB1041..
2N5858	Si-NPN	=2N5856:80V	8a	-	BC639,2SD667,2SD1226,2SD1768..
2N5859	Si-NPN	Sw,80V,2A,1W,>250MHz,<36/70nS	2a$	Mot,Sca,Ssi	BSS14,2N5262
2N586	Ge-PNP	AF,Sw,45V,Ueb=25V,0,25A,0,25W	1a	USA	ASY76..77,2N1191..94
2N5860	Si-NPN	Sw,90V,2A,1W,>250MHz,<26/70nS	2a$	Sca,Ssi	-
2N5861	Si-NPN	Sw,100V,2A,1W,>200MHz,<26/70nS	2a$	Mot,Sca,Ssi	-
2N5862	Si-NPN	VHF-Pow,65V,8A,Pq=90W(150MHz)	55r	Mot,Tix	-
2N5864	Si-PNP	GenP,90V,1,5A,1,25W,<130/750nS	2a$	USA,Mot	BCX60,BSS17,BSV17,2N5322
2N5865	Si-PNP	GenP,70V,1A,1,25W,<120/500nS	2a$	USA,Mot	BCX60,BSS17,BSX59..61,2N3444..
2N5867	Si-PNP	AF,Sw-Pow,60V,5A,87,5W,>4MHz	23a$	USA,Mot,Tix	BD246A,BDV92,BDW52C,BDX92,2N5871..72..
2N5868	Si-PNP	=2N5867:80V	23a$	-	BD246B,BDV94,BDW52C,BDX94,2N5872..
2N5869	Si-NPN	AF,Sw-Pow,60V,5A,87,5W,>4MHz	23a$	USA,Mot,Tix	BD245A,BDV91,BDW51C,BDX91,2N5873..74..
2N587	Ge-NPN	AF,Sw,40/20/40V,0,2A,0,15W	2a&	USA	-
2N5870	Si-NPN	=2N5869:80V	23a$	-	BD245B,BDV93,BDW51C,BDX93,2N5874..
2N5871	Si-PNP	AF,Sw-Pow,60V,7A,115W,>4MHz	23a$	USA,Mot,Sgs	BD312,BD546A,BDW22A,2N5875..76,+
2N5872	Si-PNP	=2N5871:80V	23a$	-	BD314,BD546B,BDW22B,BDW52C,2N5876..
2N5873	Si-NPN	AF,Sw-Pow,60V,7A,115W,>4MHz	23a$	USA,Mot,Sgs	BD545A,BD311,BDW21A,2N5877..78..
2N5874	Si-NPN	=2N5873:80V	23a$	-	BD545A,BD313,BDW21B,BDW51C,2N5878..
2N5875	Si-PNP	AF,Sw-Pow,60V,10A,150W,>4MHz	23a$	USA,Mot,Sgs	BD312,BD546A,BDW22A,2N5879..80,+
2N5876	Si-PNP	=2N5875:80V	23a$	-	BD314,BD546B,BDW22B,BDW52C,2N5880..
2N5877	Si-NPN	AF,Sw-Pow,60V,10A,150W,>4MHz	23a$	USA,Mot,Sgs	BD311,BD545A,BDW21A,2N5881..82..
2N5878	Si-NPN	=2N5877:80V	23a$	-	BD313,BD545B,BDW21B,2N5882..
2N5879	Si-PNP	AF,Sw-Pow,60V,15A,160W,>4MHz	23a$	USA,Mot,Rca	BD316,BD746A,BDW52A,2N6029..31..
2N588(A)	Ge-PNP	HF,15V,0,05A,250MHz	2a	USA	AF106,AF109R,AF306
2N5880	Si-PNP	=2N5879:80V	23a$	-	BD316,BD746B,BDW52B,2N6029..31..
2N5881	Si-NPN	AF,Sw-Pow,60V,15A,160W,>4MHz	23a$	USA,Mot,Rca	BD315,BD745A,BDW51A,2N5620..31,+
2N5882	Si-NPN	=2N5881:80V	23a$	-	BD315,BD745B,BDW51B,2N5620..31..
2N5883	Si-PNP	AF,Sw-Pow,60V,25A,200W,>4MHz	23a$	USA,Mot,Sgs	BD367,BD369,MJ4502,2N4399
2N5884	Si-PNP	=2N5883:80V	23a$	-	2N5884,BD369,MJ4502
2N5885	Si-NPN	AF,Sw-Pow,60V,25A,200W,>4MHz	23a$	USA,Mot,Sgs	BD366,BD368,BDY29,MJ802..
2N5886	Si-NPN	=2N5885:80V	23a$	-	BD368,BDY29,MJ802,2N5886,2SD797..
2N5887	Ge-PNP	AF,Sw-Pow,20V,7A,57W,B>15	22a$	Gpd,Mot,Stc	-

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2N5888	Ge-PNP	=2N5887:30V	22a$	-	-
2N5889	Ge-PNP	=2N5887:30V,B>30	22a$	-	-
2N589	Ge-PNP	Sw,Pow,100V,Ueb=50V,3A,90W	23a$	USA	AL102..103,AUY34,2N1547..48..
2N5890	Ge-PNP	=2N5887:45V,B>30	22a$	-	-
2N5891	Ge-PNP	=2N5887:60V,B>30	22a$	-	-
2N5892	Ge-PNP	=2N5887:75V,B>30	22a$	-	-
2N5893	Ge-PNP	=2N5887:30V,B>60	22a$	-	-
2N5894	Ge-PNP	=2N5887:45V,B>60	22a$	-	-
2N5895	Ge-PNP	=2N5887:60V,B>60	22a$	-	-
2N5896	Ge-PNP	=2N5887:75V,B>60	22a$	-	-
2N5897	Ge-PNP	=2N5887:30V,B>100	22a$	-	-
2N5898	Ge-PNP	=2N5887:45V,B>100	22a$	-	-
2N5899	Ge-PNP	=2N5887:60V,B>100	22a$	-	-
2N59	Ge-PNP	AF,25V,0,2A,0,18W,B=90,1,8MHz	2a	USA	AC125..126,AC151,ASY26..27
2N5900	Ge-PNP	=2N5887:75V,B>100	22a$	-	-
2N5901	Ge-PNP	=2N5887:30V,B>175	22a$	-	-
2N5902	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	Isi,Nsc,Six	-
2N5903	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5904	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5905	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5906	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5907	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5908	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N5909	N-FET	Dual,LN,40V,Idss>0,03mA,Up<4,5V	81bx	-	-
2N591(/S)	Ge-PNP	AF,Sw,32V,0,04A,0,05W,0,7MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N5910	Si-PNP	Sw,20V,0,05A,0,31W,<25/30nS	8a	Fch,Mic,Nsc	BSX36
2N5911	N-FET	Dual,LN,25V,Idss>7mA,Up<5V	81bx	Isi,Nsc,Six	-
2N5912	N-FET	Dual,LN,25V,Idss>7mA,Up<6V	81bx	-	-
2N5913	Si-NPN	VHF/UHF-Dr/Out,36V,0,33A,Pq=2W(470MHz)	2a$	Rca	BLX65,MRF629,2SC2762,2SC3185
2N5914	Si-NPN	UHF-Dr/Out,36V,0,5A,Pq=2,3W(470MHz)	55s	Rca	BLW79,BLX67,BLY38,2N5945..
2N5915	Si-NPN	UHF-Dr/Out,36V,1,5A,Pq=6,5W(470MHz)	55s	Rca	BLU97,BLX68,BLY53,2SC2105
2N5916	Si-NPN	UHF-Dr/Out,55V,0,2A,Pq>2W(400MHz)	55s	Rca	BFT91,BLW89,BLY76
2N5917	Si-NPN	UHF-Dr/Out,55V,0,2A,Pq>2W(400MHz)	60e	Rca	-
2N5918	Si-NPN	UHF-Pow,60V,0,75A,Pq>10W(400MHz)	55s	Rca	MRF321,MRF331
2N5919(A)	Si-NPN	UHF-Pow,65V,4,5A,Pq>16W(400MHz)	55s	Rca	BLX95,2N6105,2SC2894
2N592	Ge-PNP	AF,Sw,Sym,20V,0,125W,>0,4MHz	2a	USA	-
2N5920	Si-NPN	UHF-Dr/Out,50V,0,275A,Pq>2W(2GHz)	Koax	Rca	-
2N5921	Si-NPN	UHF-Dr/Out,50V,0,7A,Pq>5W(2GHz)	Koax	Rca	-
2N5922	Si-NPN	UHF-Dr/Out,55V,0,425A,Pq=1W(1GHz)	55r	Mot	BLX97
2N5923	Si-NPN	UHF-Dr/Out,55V,0,75A,Pq=2,5W(1GHz)	55r	Mot	2N4430
2N5924	Si-NPN	UHF-Dr/Out,55V,1,5A,Pq=5W(1GHz)	55r	Mot	-
2N5925	Si-NPN	UHF-Pow,50V,2,5A,Pq=10W(1GHz)	55r	Mot	-
2N5926	Si-NPN	Sw,Pow,150V,50A,350W,>5MHz	49a$	USA	2N6278..81
2N5927	Si-NPN	Sw,Pow,150/120V,100A,350W,>5MHz	49a$	Sol,Ssi,Stc	2N6309..11
2N5928	Si-NPN	Sw,Pow,120/120V,100A,350W,>5MHz	49a$	Sol,Ssi,Stc	2N6309..11
2N5929	Si-NPN	Sw,Pow,90/80V,30A,175W,>30MHz	23a$	USA	BDW30,BDY29,BUX10,MJ802,2SD797
2N593	Ge-PNP	AF,Sw,Sym,40V,0,125W,>0,6MHz	2a	USA	-
2N5930	Si-NPN	=2N5929:130/120V	23a$	-	BDW30,BDY58,BUX10,2N5672
2N5931	Si-NPN	=2N5929:170/160V	23a$	-	BDW34,BDW36
2N5932	Si-NPN	Sw,Pow,70/60V,30A,175W,>30MHz	23a$	USA	BDW30,BDY29,BUX10,MJ802,2SD797..
2N5933	Si-NPN	=2N5931:110/100V	23a$	-	BDW30,BDY58,BUX10,2N5672
2N5934	Si-NPN	=2N5931:150/140V	23a$	-	BDW32,BDY58,2N5672
2N5935	Si-NPN	Sw,Pow,90/80V,30A,175W,>30MHz	23a$	USA	BDW30,BDY29,MJ802,2SD797..
2N5936	Si-NPN	=2N5935:130/120V	23a$	-	BDW30,BDY58,BUX10,2N5672
2N5937	Si-NPN	=2N5935:170/160V	23a$	-	BDW34,BDW36
2N5938	Si-NPN	RadH,60V,3A,20W(Tc=100°),>150MHz	49a	TI	-
2N5939	Si-NPN	RadH,80V,10A,40W(Tc=100°),>120MHz	49a	Ker,Stc,Tix	-
2N594	Ge-NPN	AF,Sw,Sym,20V,0,1W,>1,5MHz	2a	Ssi,Tix	-
2N5940	Si-NPN	=2N5939:RadH,70V	49a	-	-
2N5941(T)	Si-NPN	AM-Pow,65V,6A,Pep=40W(30MHz)	59r	Mot,Tix	-
2N5942	Si-NPN	AM-Pow,65V,12A,Pep=80W(30MHz)	59r	Mot,Tho,Tix	MRF463..464
2N5943	Si-NPN	UHF-A/Dr,40V,0,4A,1W,1550MHz	2a$	Mot,Tho	BFS50,MRF629,2N3948,2SC2852..
2N5944	Si-NPN	UHF-Dr/Out,36V,0,4A,Pq=2W(470MHz)	55r	Mot,Tho,Trw	BLW79
2N5945	Si-NPN	UHF-Pow,36V,0,8A,Pq=4W(470MHz)	55r	Mot,Tho,Trw	BLU97,BLW43,BLW80

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2N5946	Si-NPN	UHF-Pow,36V,2A,Pq=10W(470MHz)	55r	Mot,Tho,Trw	BLW81,2SC2106
2N5947	Si-NPN	VHF/UHF-A/Dr,40V,0,4A,5W,1,5GHz	55r	Mot	BFT91,BLW89,MRF313
2N5949	N-FET	GenP,LN,30V,Idss>12mA,Up<7V	7b	Nsc,Tix,Tsc	BF244C..245C,BF256C,BFT10A..
2N595	Ge-NPN	AF,Sw,Sym,15V,0,1W,>3MHz	2a	Ssi,Tix	-
2N5950	N-FET	GenP,LN,30V,Idss>10mA,Up<6V	7b	Nsc,Tix,Tsc	BF256C,BF348,BFT10A,2N5397,2N5486
2N5951	N-FET	GenP,LN,30V,Idss>7mA,Up<5V	7b	Nsc,Tix,Tsc	BF256B
2N5952	N-FET	GenP,LN,30V,Idss>4mA,Up<3,5V	7b	Nsc,Tix,Tsc	BC264,BF410C,2N5485,2SK147,2SK168
2N5953	N-FET	GenP,LN,30V,Idss>2,5mA,Up<3V	7b	Nsc,Tix,Tsc	BC264,BF410B,2SK192,2SK370
2N5954	Si-PNP	AF,Sw-Pow,90V,6A,40W,>5MHz	22a$	Rca,Stc,Tra	BD244C,BDS44C,BD802,2N6318..
2N5955	Si-PNP	=2N5954:70V	22a$	-	BD244B,BDS44B,BD800,2N6318..
2N5956	Si-PNP	=2N5954:50V	22a$	-	BD244A,BDS44A,BD798,2N6317..
2N5957	Si-NPN	Sw,Pow,100V,20A,150W,>10MHz	49a$	USA	-
2N5958	Si-PNP	Sw,Pow,100V,20A,150W,>10MHz	49a$	USA	-
2N5959	Si-NPN	=2N5957:Iso	49a	-	-
2N596	Ge-NPN	AF,Sw,Sym,10V,0,1W,>5MHz	2a	Ssi,Tix	-
2N5960	Si-PNP	=2N5958:Iso	49a	-	-
2N5961	Si-NPN	GenP,LN,60V,0,05A,0,625W,B>150	7e	Fch,Nsc	BC174,BC182,BC190,BC546..
2N5962	Si-NPN	=2N5961:45V,B>600	7e	Fch,Nsc	2SC3495
2N5963	Si-NPN	=2N5961:30V,B>1200	7e	Fch	2SC3495
2N5964	Si-NPN	Vid,160V,0,6A,0,7W,>100MHz	2a	Fch	BF391..393,BFP22,MPSA43,2SD624..
2N5965	Si-NPN	=2N5964:200V	2a	Fch	BF391..393,BFP22,MPSA43,2SD624..
2N5966	Si-NPN	Sw,Pow,100/100V,30A,187W,>10MHz	49a$	USA	2N2824..25
2N5967	Si-PNP	Sw,Pow,100/100V,30A,187W,>10MHz	49a$	USA	-
2N5968	Si-NPN	=2N5966:Iso	49a	-	-
2N5969	Si-PNP	=2N5967:Iso	49a	-	-
2N597	Ge-PNP	AF,Sw,45/40/45V,0,5A,0,25W,>3MHz	2a	USA	(ASY76..77)
2N5970	Si-NPN	Sw,Pow,80/60V,15A,150W,>4MHz,B>20	23a$	USA	BD315,BDS45B,BDW51C,2N3772,2N5629..31..
2N5971	Si-NPN	=2N5970:B>50	23a$	-	BD315,BDS45B,BDW51C,2N3772,2N5629..31..
2N5972	Si-NPN	=2N5970:100/80V	23a$	-	BD317,BDS45C,2N3772,2N5629..31..
2N5973	Si-NPN	=2N5970:120/100V	23a$	-	BDX50,BDS45D,2N3773,2N5630..31,2N5886...
2N5974	Si-PNP	AF,Sw-Pow,60V,5A,75W,>2MHz	16h$	Mot	BD200,MJE2955T,2N5980,2SB579
2N5975	Si-PNP	=2N5974:80V	16h$	-	2N5981,2SB580,MJE2955T
2N5976	Si-PNP	=2N5974:100V	16h$	-	2N5982,2SB581,MJE2955T
2N5977	Si-NPN	AF,Sw-Pow,60V,5A,75W,>2MHz	16h$	Mot	BD199,MJE3055T,2N5983,2SD493
2N5978	Si-NPN	=2N5977:80V	16h$	-	2N5984,2SD494,MJE3055T
2N5979	Si-NPN	=2N5977:100V	16h$	-	2N5985,2SD495,MJE3055T
2N598	Ge-PNP	AF,Sw,35/35/30V,0,5A,0,25W,>5,6MHz	2a	USA	(ASY76..77)
2N5980	Si-PNP	AF,Sw-Pow,60V,8A,90W,>2MHz	16h$	Mot	BD208,MJE2955T,2N5986,2SB578
2N5981	Si-PNP	=2N5980:80V	16h$	-	2N5987,MJE2955T
2N5982	Si-PNP	=2N5980:100V	16h$	-	2N5988,2N6490
2N5983	Si-NPN	AF,Sw-Pow,60V,8A,90W,>2MHz	16h$	Mot	BD207,MJE3055T,2N5989,2SD491
2N5984	Si-NPN	=2N5983:80V	16h$	-	2N5990,MJE3055T
2N5985	Si-NPN	=2N5983:100V	16h$	-	2N5991,TIP33C
2N5986	Si-PNP	AF,Sw-Pow,60V,12A,100W,>2MHz	16h$	Mot	2N6490
2N5987	Si-PNP	=2N5986:80V	16h$	-	2N6490
2N5988	Si-PNP	=2N5986:100V	16h$	-	-
2N5989	Si-NPN	AF,Sw-Pow,60V,12A,100W,>2MHz	16h$	Mot	-
2N599	Ge-PNP	AF,Sw,30/20/20V,0,5A,0,25W,>10MHz	2a	USA	(ASY76..77)
2N5990	Si-NPN	=2N5989:80V	16h$	-	TIP33C
2N5991	Si-NPN	=2N5989:100V	16h$	-	TIP33C
2N5992	Si-NPN	FM/VHF-Pow,65V,5A,Pq>7W(88MHz)	55s	Rca	-
2N5993	Si-NPN	FM/VHF-Pow,36V,5A,Pq=20W(88MHz)	55s	Rca	-
2N5994	Si-NPN	VHF-Pow,65V,5A,Pq=35W(175MHz)	55s	Rca	BLW25,2N5643,2SC2889
2N5995	Si-NPN	VHF-Pow,36V,1,5A,Pq>7W(175MHz)	55s	Rca	2SC2281
2N5996	Si-NPN	VHF-Pow,36V,5A,Pq>15W(175MHz)	55s	Rca	BLW20,BLW31,2N6084
2N5998	Si-NPN	AF-Pre,LN,35V,0,5A,0,4W,300MHz	7c	Gen,Sem,Spr	BC184,BC239,BC337..338,BC549..
2N5999	Si-PNP	AF-Pre,LN,35V,0,5A,0,4W,300MHz	7c	Gen,Sem,Spr	BC214,BC309,BC327..328,BC559..
2N59A	Ge-PNP	=2N59:40V	2a	-	ASY48,ASY76..77
2N59B	Ge-PNP	=2N59:50V	2a	-	ASY48,ASY77
2N59C	Ge-PNP	=2N59:60V	2a	-	ASY48,ASY77
2N600	Ge-PNP	AF,Sw,35V,Ueb=30V,0,5A,0,75W,10MHz	37d$	Idi,Ssi	(AC128K,AC153K,ASY76..77)
2N6000	Si-NPN	GenP,LN,35V,0,5A,0,4W,B>100	7a	Gen,Sem	BC184,BC239,BC337..338,BC549..
2N6001	Si-PNP	GenP,LN,35V,0,5A,0,4W,B>100	7a	Gen,Sem	BC214,BC309,BC327..328,BC559..
2N6002	Si-NPN	=2N6000:B>250	7a	-	BC184,BC239,BC337..338,BC549..

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2N6003	Si-PNP	=2N6001:B>250	7a	-	BC214,BC309,BC327..328,BC559..
2N6004	Si-NPN	GenP,LN,50V,0,5A,0,4W,B>100	7a	Gen,Sem	BC337,BC414,BC550,BC637..
2N6005	Si-PNP	GenP,LN,50V,0,5A,0,4W,B>100	7a	Gen,Sem	BC327,BC416,BC560,BC638..
2N6006	Si-NPN	=2N6004:B>250	7a	-	BC337,BC414,BC550,BC637..
2N6007	Si-PNP	=2N6005:B>250	7a	-	BC327,BC416,BC560,BC638..
2N6008	Si-NPN	AF,LN,35V,0,5A,0,4W,300MHz	7c	Gen,Sem,Spr	BC184,BC239,BC337..338,BC549..
2N6009	Si-PNP	AF,LN,35V,0,5A,0,4W,300MHz	7c	Gen,Sem,Spr	BC214,BC309,BC327..328,BC559..
2N601	Ge-PNP	AF,Sw,30V,Ueb=20V,0,5A,0,75W,18MHz	37d$	Idt,Ssi	(AC128K,AC153K,ASY76..77)
2N6010	Si-NPN	GenP,LN,50V,0,8A,0,5W,B>100	7a	Gen,Sem	BC337,BC637,BSV59,2N2221..22(A),..
2N6011	Si-PNP	GenP,LN,50V,0,8A,0,5W,B>100	7a	Gen,Sem	BC327,BC638,BSW24,2N2906..07(A),..
2N6012	Si-NPN	=2N6010:B>250	7a	-	BC337,BC637,BSV59,2N2221..22(A),..
2N6013	Si-PNP	=2N6011:B<250	7a	-	BC327,BC638,BSW24,2N2906..07(A),..
2N6014	Si-NPN	GenP,LN,70V,0,8A,0,5W,B>100	7a	-	BC639,BSV59,2N2221..22A,2SD667..
2N6015	Si-PNP	GenP,LN,70V,0,8A,0,5W,B>100	7a	-	BC640,BSW24,2N2906..07A,2SB647..
2N6016	Si-NPN	=2N6014:B>250	7a	-	BC639,BSV59,2N2221..22A,2SD667..
2N6017	Si-PNP	=2N6015:B>250	7a	-	BC640,BSW24,2N2906..07A,2SB647..
2N602(A)	Ge-PNP	HF,20(A:35)V,0,12W,20MHz	2a	USA	AF124..126,AF200
2N6021	Si-PNP	AF,Sw-Pow,80/70V,4A,36W,>0,8MHz	17j$	Sem	BD244B,BD538,BD540B,BD952,TIP32C…
2N6022	Si-PNP	=2N6021	17j$	-	BD244B,BD538,BD540B,BD952,TIP32C…
2N6023	Si-PNP	=2N6021:60/40V	17j$	-	BD244A,BD536,BD540A,BD950,TIP32B…
2N6024	Si-PNP	=2N6021:60/40V	17j$	-	BD244A,BD536,BD540A,BD950,TIP32B…
2N6025	Si-PNP	=2N6021:80/60V	17j$	-	BD244B,BD538,BD540B,BD952,TIP32B…
2N6026	Si-PNP	=2N6021:80/60V	17j$	-	BD244B,BD538,BD540B,BD952,TIP32B…
2N6027	PUT	Ip<5µA,Iv>70µA	7a(KGA)	Gen,Mot,Phi	2N6116,2N6119,MPU131,MPU231
2N6028	PUT	=2N6027:Ip<1?A,Iv>25?A	7a(KGA)	-	2N6120
2N6029	Si-PNP	AF,Sw-Pow,100V,16A,200W,>1MHz	23a$	Fch,Mot,Stc	BD318,2N6609,2SA1117
2N603(A)	Ge-PNP	HF,30V,0,12W,40MHz,A:>12MHz	2a	USA	AF124..126,AF200
2N6030	Si-PNP	=2N6029:120V	23a$	-	MJ15016,2N6609,2SA1117
2N6031	Si-PNP	=2N6029:140V	23a$	-	MJ15016,2N6609,2SA1117
2N6032	Si-NPN	Sw,Pow,120/90V,50A,140W,>50MHz	23a$	USA,Rca	2N6275..77,BUV20
2N6033	Si-NPN	Sw,Pow,150/120V,40A,140W,>50MHz	23a$	USA,Rca	2N6275..77,BUV21
2N6034	Si-P-Darl+Di	AF,Sw-Pow,40V,4A,40W,B>750	14h$	Mot,Nsc,Sgs	BD676,BD776
2N6035	Si-P-Darl+Di	=2N6034:60V	14h$	-	BD678,BD778
2N6036	Si-P-Darl+Di	=2N6034:80V	14h$	-	BD680,BD780
2N6037	Si-N-Darl+Di	AF,Sw-Pow,40V,4A,40W,B>750	14h$	Mot,Nsc,Sgs	BD675,BD681,BD775
2N6038	Si-N-Darl+Di	=2N6037:60V	14h$	-	BD677,BD681,BD777
2N6039	Si-N-Darl+Di	=2N6037:80V	14h$	-	BD679,BD681,BD779
2N604(A)	Ge-PNP	HF,30V,0,12W,60MHz,A:>12MHz	2a	USA	AF124..126,AF200
2N6040	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,75W,B>1000	17j$	Mot,Nsc,Rca	BD646,BD898,BDW74A,BDX54A..
2N6041	Si-P-Darl+Di	=2N6040:80V	17j$	-	BD648,BD900,BDW74B,BDX54B..
2N6042	Si-P-Darl+Di	=2N6040:100V	17j$	-	BD650,BD902,BDW74C,BDX54C,TIP107…
2N6043	Si-N-Darl+Di	AF,Sw-Pow,60V,8A,75W,B>1000	17j$	Mot,Nsc,Rca	BD645,BD897,BDW73A,BDX53A..
2N6044	Si-N-Darl+Di	=2N6043:80V	17j$	-	BD647,BD899,BDW73B,BDX53B..
2N6045	Si-N-Darl+Di	=2N6043:100V	17j$	-	BD649,BD901,BDW73C,BDX53C,TIP102…
2N6046	Si-NPN	Sw,Pow,70V,20A,114W(Tc=100°),>30MHz	49a$	USA,Trw	2N2815..18,2N2819..22
2N6047	Si-NPN	=2N6046:110V	49a$	-	2N2817..18,2N2821..22
2N6048	Si-NPN	=2N6046:150V	49a$	-	2N2817..18,2N2821..22
2N6049	Si-PNP	AF,Sw-Pow,90V,4A,75W,>3MHz	22a$	USA,Mot	BD244C,BD540C,BD954,BDX14..
2N605	Ge-PNP	HF,15V,0,12W,15MHz	2a	Sty	AF124..127,AF200
2N6050	Si-P-Darl+Di	AF,Sw-Pow,60V,12A,150W,B>750	23a$	Fch,Mot,Rca	BDV66,BDW84A,BDX64,BDX88A..
2N6051	Si-P-Darl+Di	=2N6050:80V	23a$	-	BDV66A,BDW84B,BDX64A,BDX88B..
2N6052	Si-P-Darl+Di	=2N6050:100V	23a$	-	BDV66A,BDW84C,BDX64B,BDX88C..
2N6053	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,100W,B>750	23a$	Fch,Mot,Rca	BDV64,BDX62,MJ900,TIP145..
2N6054	Si-P-Darl+Di	=2N6053:80V	23a$	-	BDV64A,BDX62A,MJ901,TIP146..
2N6055	Si-N-Darl+Di	AF,Sw-Pow,60V,8A,100W,B>750	23a$	Fch,Mot,Rca	BDV65,BDX63,MJ1000,TIP140..
2N6056	Si-N-Darl+Di	=2N6055:80V	23a$	-	BDV65A,BDX63A,MJ1001,TIP141..
2N6057	Si-N-Darl+Di	AF,Sw-Pow,60V,12A,150W,B>750	23a$	Fch,Mot,Rca	BDV67,BDW83A,BDX65,BDX87A..
2N6058	Si-N-Darl+Di	26057:80V	23a$	-	BDV67A,BDW83B,BDX65A,BDX87B..
2N6059	Si-N-Darl+Di	=2N6057:100V	23a$	-	BDV65A,BDW83C,BDX65B,BDX87C..
2N606	Ge-PNP	HF,15V,0,12W,20MHz	2a	Sty	AF124..127,AF200
2N6060	Si-NPN	Sw,Pow,100/100V,50A,225W,>10MHz	49a$	USA	2N6278..81
2N6061	Si-PNP	Sw,Pow,100/100V,50A,225W,>10MHz	49a$	USA	2N6380..82
2N6062	Si-NPN	=2N6060:Iso	49a	-	-
2N6063	Si-PNP	=2N6061:Iso	49a	-	-

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2N6064	Ge-PNP	Sw,Pow,80V,10A,56W	?2a$	Mot	-
2N6065	Ge-PNP	=2N6064:120V	?2a$	-	-
2N6066	Ge-PNP	=2N6064:160V	?2a$	-	-
2N6067	Si-PNP	Sw,50V,1A,0,625W,<45/95nS	7e	Mot	2N4026..29
2N6068	Triac	25V,4A(Tc=85°),Igt/Ih<30/<30mA	14h$	Mot,Tag	TAG96A,(TAG136A,Z0410A,TAG231-200)
2N6068..6075A	Triac	=2N6068..6075:Igt/Ih<10/<15mA	14h$	-	TAG97..(TAG137..Z0409..TAG232..)
2N6068..6075B	Triac	=2N6068..6075:Igt/Ih<5/<15mA	14h$	-	TAG98..(TAG138..Z0405..TAG233..)
2N6069	Triac	=2N6068:50V	14h$	-	TAG96A,(TAG136A,Z0410A,TAG231-200)
2N607	Ge-PNP	HF,15V,0,12W,25MHz	2a	Sty	AF124..126,AF200
2N6070	Triac	=2N6068:100V	14h$	-	TAG96A,(TAG136A,Z0410A,TAG231-200)
2N6071	Triac	=2N6068:200V	14h$	-	TAG96B,(TAG136B,Z0410B,TAG231-200)
2N6072	Triac	=2N6068:300V	14h$	-	TAG96C,(TAG136C,Z0410C,TAG231-400)
2N6073	Triac	=2N6068:400V	14h$	-	TAG96D,(TAG136D,Z0410D,TAG231-400)
2N6074	Triac	=2N6068:500V	14h$	-	TAG96E,(TAG136E,Z0410E,TAG231-600)
2N6075	Triac	=2N6068:600V	14h$	-	TAG96M,(TAG136M,Z0410M,TAG231-600)
2N6076	Si-PNP	GenP,25V,0,1A,0,36W,200MHz	7c	USA,Gen,Nsc	BC213,BC258,BC308,BC558..
2N6077	Si-NPN	Sw,Pow,300/275V,7A,45W,7MHz	22a$	USA,Mot,Rca	BU406..408,BUT56(A),2SC1865..
2N6078	Si-NPN	Sw,Pow,275/250V,7A,45W,7MHz	22a$	-	BU406..408,BUT56(A),2SC1865..
2N6079	Si-NPN	Sw,Pow,375/350V,7A,45W,7MHz	22a$	-	BU406,BU408,BUT56(A),2SC1865..
2N608	Ge-PNP	HF,15V,0,12W,35MHz	2a	Sty	AF124..126,AF200
2N6080	Si-NPN	VHF-Dr/Out,36V,1A,Pq=4W(175MHz)	55r	Mot,Sem,Tho	BLY85
2N6081	Si-NPN	VHF-Pow,36V,2,5A,Pq=15W(175MHz)	55r	=2N6080	BLW29,BLY84,BLY88,MRF226
2N6082	Si-NPN	VHF-Pow,36V,5A,Pq=25W(175MHz)	55r	=2N6080	BLY89,MRF209,2N5591
2N6083	Si-NPN	VHF-Pow,36V,5A,Pq=30W(175MHz)	55r	=2N6080	MRF238
2N6084	Si-NPN	VHF-Pow,36V,7A,Pq=40W(175MHz)	55r	=2N6080	BLW60
2N6085	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6086	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6087	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6088	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6089	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N609	Ge-PNP	AF,25V,0,2A,0,18W,1,2MHz,B=100	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6090	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6091	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6092	Si-NPN	Dual,45V,0,03A,0,6W,>60MHz	81bs	Tsc	2N3728..29,2N3411
2N6093	Si-NPN	AM/SSB-Pow,70V,10A,Pep=75W(30MHz)	-	Rca,Tho	-
2N6094	Si-PNP	VHF-Pow,36V,1A,Pq=4W(175MHz)	59r	Mot	-
2N6095	Si-PNP	VHF-Pow,36V,2,5A,Pq=15W(175MHz)	59r	Mot	-
2N6096	Si-PNP	VHF-Pow,36V,4A,Pq=30W(175MHz)	59r	Mot	-
2N6097	Si-PNP	VHF-Pow,36V,4A,Pq=40W(175MHz)	59r	Mot	-
2N6098	Si-NPN	AF,Sw-Pow,70V,10A,75W,>0,8MHz	17jS	USA,Rca,Tho	2N6487,BD709,BD743A,BD807,BD909..
2N6099	Si-NPN	=2N6098	17jS	-	2N6487,BD709,BD743A,BD807,BD909..
2N60A..C	Ge-PNP	=2N59A..C:B=65,1,5MHz	2a	USA	→2N59A..C
2N610	Ge-PNP	=2N609:1,1MHz,B=80	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6100	Si-NPN	=2N6098:80V	17jS	-	2N6487,BD709,BD743B,BD809,BD909..
2N6101	Si-NPN	=2N6098:80V	17jS	-	2N6488,BD709,BD743B,BD809,BD909..
2N6102	Si-NPN	=2N6098:45V,16A	17jS	-	2N6488,BD743,BD905,BDT81
2N6103	Si-NPN	=2N6098:45V,16A	17jS	-	2N6487,BD743,BD905,BDT81
2N6104	Si-NPN	UHF-Pow,65V,4,5A,Pq>30W(400MHz)	60e*	Rca	-
2N6105	Si-NPN	UHF-Pow,65V,4,5A,Pq>30W(400MHz)	55s	-	-
2N6106	Si-PNP	AF,Sw-Pow,80V,7A,40W,>10MHz	17jS	USA,Mic,Mot	BD244B,BD544B,BD800,BD810..
2N6107	Si-PNP	=2N6106	17jS	-	BD244B,BD544B,BD800,BD810..
2N6108	Si-PNP	=2N6106:60V	17jS	-	BD244A,BD544A,BD798,BD808..
2N6109	Si-PNP	=2N6106:60V	17jS	-	BD244A,BD544A,BD798,BD808..
2N611	Ge-PNP	=2N609:1MHz,B=60	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6110	Si-PNP	=2N6106:40V	17jS	-	BD244,BD544,BD796,BD806..
2N6111	Si-PNP	=2N6106:40V	17jS	-	BD244,BD544,BD796,BD806..
2N6112	Si-NPN	GenP,50V,0,36W,>160MHz	10b	Upi	BC167,BC182,BC237,BC547..
2N6114	UJT-N	Ip<5μA,Iv>1mA	5r	Gen,Mot	-
2N6115	UJT-N	=2N6114:Ip<15?A	5r	-	-
2N6116	PUT	Ip<5μA,Iv>70μA	2a(KGA)	Gen,Mot	2N6027,2N6119,MPU131,MPU231
2N6117	PUT	=2N6116:Ip<2?A,Iv>50?A	2a(KGA)	-	MPU132,MPU232
2N6118	PUT	=2N6116:Ip<1?A,Iv>50?A	2a(KGA)	-	MPU133,MPU233
2N6119	PUT	Ip<5μA,Iv>70μA	2a$(KGA)	Uni	2N6027,2N6116,MPU131,MPU231
2N612	Ge-PNP	=2N609:0,6MHz,B=25	2a	USA	AC125..126,AC151,2SB54,2SB56

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2N6120	PUT	=2N6119: Ip<1?A, Iv>25?A	2a$(KGA)	-	2N6028
2N6121	Si-NPN	AF, Sw-Pow, 45V, 4A, 40W, >2,5MHz	17j$	Fch,Mic,Mot	BD243, BD533, BD539, BD947, +
2N6122	Si-NPN	=2N6121: 60V	17j$	-	BD243A, BD535, BD539A, BD949, TIP31C...
2N6123	Si-NPN	=2N6121: 80V	17j$	-	BD243B, BD537, BD539B, BD951..
2N6124	Si-PNP	AF, Sw-Pow, 45V, 4A, 40W, >2,5W	17j$	=2N6121	BD244, BD534, BD540, BD948..
2N6125	Si-PNP	=2N6124: 60V	17j$	-	BD244A, BD536, BD540A, BD950, TIP32B...
2N6126	Si-PNP	=2N6124: 80V	17j$	-	BD244B, BD538, BD540B, BD952..
2N6127	Si-PNP	Sw, Pow, 100V, 10A, 100W(Tc=50°), >40MHz	49a	Ker,Sol,Ssi	2N5290..91
2N6128	Si-NPN	Sw, Pow, 100V, 10A, 100W(Tc=50°), >50MHz	49a	Ker,Sol,Ssi	2N5288..89
2N6129	Si-NPN	AF, Sw-Pow, 40V, 7A, 50W, >2,5MHz	17j$	Fch,Mic,Nsc	BD543, BD705, BD795, BD805, +
2N613	Ge-PNP	=2N609: 0,85MHz, B=33	2a	USA	AC125..126, AC151, 2SB54, 2SB56
2N6130	Si-NPN	=2N6129: 60V	17j$	-	BD543A, BD707, BD797, BD807, TIP41B...
2N6131	Si-NPN	=2N6129: 80V	17j$	-	BD543B, BD709, BD799, BD809, TIP41B...
2N6132	Si-PNP	AF, Sw-Pow, 40V, 7A, 50W, >2,5MHz	17j$	=2N6129	BD544, BD706, BD796, BD806, TIP42C...
2N6133	Si-PNP	=2N6132: 60V	17j$	-	BD544A, BD708, BD798, BD808, TIP42C...
2N6134	Si-PNP	=2N6132: 80V	17j$	-	BD544B, BD710, BD800, BD810, TIP42C...
2N6135	Si-NPN	UHF, 35V, 0,25A, 2,5W, >1100MHz	-	Mot	-
2N6136	Si-NPN	UHF-Pow, 36V, 6A, Pq=25W(470MHz)	55r	Mot	2SC1339, 2SC2173
2N6137	PUT	Iv>70µA	2a$(KGA)	Mot,Uni	-
2N6138	PUT	=2N6138	2a$(KGA)	-	-
2N6139	Triac	200V, 10A(Tc=75°), Igt/Ih<75/<40mA	21b$	Mot	T4110E, 2N5573, T6411B, 2N6160, T6410B
2N614	Ge-PNP	HF/Sw, 20V, 0,15A, 0,125W, 3MHz	2a	USA	ASY26..27, ASY76..77
2N6140	Triac	=2N6139: 400V	21b$	-	T4110E, 2N5574, T6411D, 2N6161, T64100
2N6141	Triac	=2N6139: 600V	21b$	-	T4110M, T6411M, 2N6162, T6410M, 2N5446
2N6142	Triac	=2N6139	21b$	-	→2N6139
2N6143	Triac	=2N6140	21b$	-	→2N6140
2N6144	Triac	=2N6141	21b$	-	→2N6141
2N6145	Triac	=2N5571	54b	Mot	T6421B, 2N6163, T6420B
2N6146	Triac	=2N5572	54b	Mot	T6421D, 2N6164, T64200
2N6147	Triac	=T4100M	54b	Mot	T6421M, 2N6165, T6420M
2N615	Ge-PNP	HF/Sw, 20V, 0,15A, 0,125W, 5MHz	2a	USA	ASY26..27, ASY76..77
2N6151	Triac	=2N6139	16h$	Mot	-
2N6152	Triac	=2N6140	16h$	Mot	-
2N6153	Triac	=2N6141	16h$	Mot	-
2N6154	Triac	200V, 10A, Igt<50mA	16h$	Mot	-
2N6155	Triac	=2N6154: 400V	16h$	Mot	-
2N6156	Triac	=2N6154: 600V	16h$	Mot	-
2N6157	Triac	200V, 30A(Tc=85°), Igt/Ih<100/<80mA	29b$	Mot	T6401B, T6400B, 2N5441
2N6158	Triac	=2N6157: 400V	29b$	-	T6401D, T6400D, 2N5442
2N6159	Triac	=2N6157: 600V	29b$	-	T6401M, T6400M, 2N5443
2N616	Ge-PNP	HF/Sw, 15V, 0,15A, 0,125W, 9MHz	2a	USA	ASY26..27, ASY76..77
2N6160	Triac	=2N6157	21b$	-	T6411B, T6410B, 2N5444
2N6161	Triac	=2N6158	21b$	-	T6411D, T64100, 2N5445
2N6162	Triac	=2N6159	21b$	-	T6411M, T6410M, 2N5446
2N6163	Triac	=2N6157: Iso	54b	-	T6421B, T6420B
2N6164	Triac	=2N6158: Iso	54b	-	T6421D, T64200
2N6165	Triac	=2N6159: Iso	54b	-	T6421M, T6420M
2N6166	Si-NPN	VHF-Pow, 65V, 9A, Pq=100W(150MHz)	59r	Mot,Tix	BLW78
2N6167	Thy-50Hz	100V, 13A(Tc=65o), Igt/Ih<40/50mA	54b	Mot	2N6171, MCR65-3
2N6168	Thy-50Hz	=2N6167: 200V	54b	-	2N6172, MCR65-4
2N6169	Thy-50Hz	=2N6167: 400V	54b	-	2N6173, MCR65-6
2N617	Ge-PNP	HF/Sw, 15V, 0,15A, 0,125W, 7,5MHz	2a	USA	ASY26..27, ASY76..77
2N6170	Thy-50Hz	=2N6167: 600V	54b	-	2N6174, MCR65-8
2N6171	Thy-50Hz	=2N3870	54b	Mot	MCR65-3
2N6172	Thy-50Hz	=2N3871	54b	-	MCR65-4
2N6173	Thy-50Hz	=2N3872	54b	-	MCR65-6
2N6174	Thy-50Hz	=2N3873	54b	-	MCR65-8
2N6175	Si-NPN	AF/Vid-Pow, 300V, 1A, 20W, >21MHz	14g$	Rca	(BD410, BUV63, 2SC3051, 2SC3425,..)
2N6176	Si-NPN	=2N6175: 350V	14g$	Rca	(BD410, BUV63, 2SC3051, 2SC3425,..)
2N6177	Si-NPN	=2N6175: 450V	14g$	Rca	MJE340
2N6178	Si-NPN	AF, Sw-Pow, 100V, 2A, 25W, >50MHz	14g$	Rca	(BD139, BD230, BD379, BD529,..)
2N6179	Si-NPN	=2N6178: 75V	14g$	-	(BD139, BD230, BD377, BD527,..)
2N618	Ge-PNP	AF, Sw-Pow, 80V, 3A, 106W	23a$	USA,Mot	2N1541..43, 2N1546..48, 2N3615..18..
2N6180	Si-PNP	AF, Sw-Pow, 100V, 2A, 25W, >50MHz	14m$	Rca	(BD140, BD231, BD380, BD530,..)

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2N6181	Si-PNP	=2N6182:75V	14m$	-	(BD140,BD231,BD378,BD528,..)
2N6182	Si-PNP	Sw,Pow,80/80V,10A,60W,>30MHz,B>30	49a$	Sca,Ssi,Stc	(2N5290..91)
2N6183	Si-PNP	=2N6182:B>60	49a$	-	(2N5290..91)
2N6184	Si-PNP	=2N6182:100V	49a$	-	(2N5290..91)
2N6185	Si-PNP	=2N6182:100V,B>60	49a$	-	(2N5290..91)
2N6186	Si-PNP	=2N6182:Iso	49a	USA,Mot	(2N5290..91)
2N6187	Si-PNP	=2N6183:Iso	49a	-	(2N5290..91)
2N6188	Si-PNP	=2N6184:Iso	49a	-	(2N5290..91)
2N6189	Si-PNP	=2N6185:Iso	49a	-	(2N5290..91)
2N619	Si-NPN	GenP,50V,Ueb=30V,0,05A,0,25W,B>9	2a	Sca	BC167,BC182,BC237,BC547..
2N6190	Si-PNP	Sw,80V,5A,10W(Tc=100°),>30MHz,B>30	2a$	Mot,Sca,Ssi	BFT35..37,BUY90
2N6191	Si-PNP	=2N6190:B>60	2a$	-	BFT35..37,BUY90
2N6192	Si-PNP	=2N6190:100V	2a$	-	BFT36..37,BUY90
2N6193	Si-PNP	=2N6190:100V,B>60	2a$	-	BFT36..37,BUY90
2N6194	Si-NPN	HF-Pow,50V,5W	62a&	Trw	-
2N6195	Si-NPN	HF-Pow,50V,10W	62a&	Trw	-
2N6196	Si-NPN	HF-Pow,50V,20W	62a&	Trw	-
2N6197	Si-NPN	HF-Pow,60V,1A,10W	55r	Ctr	-
2N6198	Si-NPN	HF-Pow,60V,2,5A,25W	55r	Ctr	-
2N6199	Si-NPN	HF-Pow,60V,5A,50W	55r	Ctr	-
2N61A..C	Ge-PNP	=2N59A..C:B=45,1MHz	2a	USA	→2N59A..C
2N62	Ge-PNP	AF,35V,0,02A,0,05W	37d	Phc	AC125..126,AC151
2N620	Si-NPN	=2N619:B>18	2a	Sca	BC167,BC182,BC237,BC547..
2N6200	Si-NPN	HF-Pow,60V,8,5A,85W	55r	Ctr	-
2N6201	Si-NPN	HF-Pow,60V,12A,140W	55r	Ctr	-
2N6202	Si-NPN	HF-Pow,60V,0,5A,10W	55r	Ctr	-
2N6203	Si-NPN	HF-Pow,60V,1A,20W	55r	Ctr	-
2N6204	Si-NPN	HF-Pow,60V,2A,40W	55r	Ctr	-
2N6205	Si-NPN	HF-Pow,60V,4A,80W	55r	Ctr	-
2N6206	Si-NPN	HF-Pow,50V,0,5A,10W	55r	Ctr	-
2N6207	Si-NPN	HF-Pow,50V,1A,20W	55r	Ctr	-
2N6208	Si-NPN	HF-Pow,50V,2A,40W	55r	Ctr	-
2N621	Si-NPN	=2N619:B>36	2a	Sca	BC167,BC182,BC237,BC547..
2N6211	Si-PNP	AF,Sw-Pow,275/225V,2A,35W,>20MHz	22a$	Mot,Rca,Stc	BUX66A..C,2SA1009(A),2SA1236,2SA1397
2N6212	Si-PNP	=2N6211:350/300V	22a$	-	BUX66B..C,2SA1009(A),2SA1236,2SA1397
2N6213	Si-PNP	=2N6211:400/350V	22a$	-	BUX66C,2SA1009A,2SA1236,2SA1397
2N6214	Si-PNP	=2N6211:450/400V	22a$	-	2N6422..23
2N6215	Si-NPN	Sw,Pow,100V,50A,125W(Tc=100°),>20MHz	49a$	Sol,Ssi,Stc	2N6060,2N6278..81
2N6216	Si-NPN	Sw,Pow,200V,10A,71W(Tc=100°),>20MHz	23a$	Ker,Stc	BUX17(A..C),BUX42..43,BUY18..
2N6217	Si-NPN	=2N6216:180V	23a$	-	BUX17(A..C),BUX42..43,BUY18..
2N6218	Si-NPN	Sw,Vid,300V,0,05A,0,5W,>50MHz	7a	Gen,Mic,Sem	BF299,BF420,BF483,2SC3468..
2N6219	Si-NPN	=2N6218:250V	7a	-	BF298..299,BF420,BF483,2SC3468..
2N622	Si-NPN	GenP,50V,Ueb=20V,0,05A,0,386W,>0,3	2a	Idi,Sca	BC167,BC182,BC237,BC547..
2N6220	Si-NPN	=2N6218:200V	7a	-	BF298..299,BF422,BF483,2SC3468..
2N6221	Si-NPN	=2N6218:150V	7a	-	BF297..299,BF422,BF483,2SC3468..
2N6222	Si-NPN	AF,60V,0,1A,0,36,B>75	7a	Gen,Sem,Spr	BC174,BC182,BC190,BC546..
2N6223	Si-PNP	AF,60V,0,1A,0,36W,B>75	7a	Gen,Sem,Spr	BC212,BC256,BC266,BC556..
2N6224	Si-NPN	=2N6222:B>150	7a	-	BC174,BC182,BC190,BC546..
2N6225	Si-PNP	=2N6223:B>150	7a	-	BC212,BC256,BC266,BC556..
2N6226	Si-PNP	AF,Sw-Pow,100V,6A,150W,>1MHz	23a$	USA,Mot	BD246C,BDV96,BDW52C,BDX96,2N6229..31..
2N6227	Si-PNP	=2N6226:120V	23a$	-	BD246D,MJ2955,2N6230..31,2SA1116..17..
2N6228	Si-PNP	=2N6226:140V	23a$	-	BD246D,MJ2955,2N6231,2SA1116..17,2SB555..
2N6229	Si-PNP	AF,Sw-Pow,100V,10A,150W,>1MHz	23a$	USA,Mot	BD318,BDW52C,2N6029..31,2SA1116..17..
2N623	Ge-PNP	HF,30V,0,04W,90MHz	-	Sty	AF124,AF106,AF200
2N6230	Si-PNP	=2N6229:120V	23a$	-	MJ15016,2N6030..31,2SA1116..17..
2N6231	Si-PNP	=2N6229:140V	23a$	-	MJ15016,2N6031,2SA1116..17,2SB555,..
2N6232	Si-NPN	Sw,Pow,140V,10A,15W(Tc=25°),>30MHz	2a$	Sca,Stc,Uni	BUY82
2N6232-4	Si-NPN	Sw,Pow,140V,10A,15W(Tc=25°),>30MHz	2a$o	-	(BUY82)
2N6233	Si-NPN	Sw,Pow,250/225V,5A,50W,>20MHz	22a$	Mot,Stc,Uni	BUT56(A),BUX63,2SC2907,2SC3035,..
2N6234	Si-NPN	=2N6233:300/275V	22a$	-	BUT56(A),BUX63,2SC2907,2SC3035,..
2N6235	Si-NPN	=2N6233:350/325V	22a$	-	BUT56(A),BUX63,2SC2907,2SC3035,..
2N6236	Thy-50Hz	30V,2,6A(Tc=90°),Igt/Ih<0,2/<5mA	14h$	Mot,Tag	MCR106-1,(C108Y,TAG108Y,S2060Y,..)
2N6237	Thy-50Hz	=2N6236:50V	14h$	-	MCR106-2,(C108F,TAG108F,S2060F,..)
2N6238	Thy-50Hz	=2N6236:100V	14h$	-	MCR106-3,(C108A,TAG108A,S2060A,..)

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2N6239	Thy-50Hz	=2N6236:200V	14h$	-	MCR106-4,(C108B,TAG108B,S2060B,..)
2N624	Ge-PNP	HF,30V,10mA,0,1W,>12MHz	5g	Etc,Syl	AF124..127,AF200
2N6240	Thy-50Hz	=2N6236:400V	14h$	-	MCR106-6,(C108D,TAG108D,S2060D,..)
2N6241	Thy-50Hz	=2N6236:600V	14h$	-	MCR106-8,(C108M,TAG108M,S2060M,..)
2N6246	Si-PNP	AF,Sw-Pow,70V,15A,125W,>6MHz	23a$	USA,Rca,Tix	BD316,BD546B,BDW52C,MJ2955,2N6029..31..
2N6247	Si-PNP	=2N6246:90V	23a$	-	BD318,BD546C,BDW52C,MJ2955,2N6029..31..
2N6248	Si-PNP	=2N6246:110V	23a$	-	BD318,BD546D,MJ2955,2N6030..31..
2N6249	Si-NPN	Sw,Pow,300/200V,10A,175W,8MHz	23a$	USA,Mot,Rca	BUX17A..C,BUW24..25,BUW72,+
2N625	Ge-NPN	AF,Sw,40V,Ueb=20V,1A	2a&	Syl	-
2N6250	Si-NPN	=2N6249:375/275V	23a$	-	BUX17B,C,BUV21,BUW24..25,BUW34,BUW72,..
2N6251	Si-NPN	=2N6249:450/350V	23a$	-	BUX17C,BUX48,BUW24..25,BUW34,BUW72..
2N6253	Si-NPN	AF,Sw-Pow,55V,15A,115W,>0,8MHz	23a$	USA,Rca,Tix	BD315,BDS45A,2N3055,2N5881..82..
2N6254	Si-NPN	AF,Sw-Pow,100V,15A,150W,>0,8MHz	23a$	USA,Rca,Tix	BD317,BDS45C,2N3772,2N5629..31..
2N6255	Si-NPN	VHF-Dr/Out,36V,1A,Pq=3W(175MHz)	2a$	Ker,Mot,Whs	BFQ43,BFS22,BFW46,2N3924
2N6256	Si-NPN	UHF-Dr/Out,36V,0,4A,Pq=0,5W(470MHz)	51r	Mot	BLU98,MRF627..628
2N6257	Si-NPN	AF,Sw-Pow,50V,20A,150W,>0,8MHz	23a$	USA,Mot,Rca	BD364,BDX40..41,2N3771..72,2N5886...
2N6258	Si-NPN	AF,Sw-Pow,100V,30A,250W,>0,8MHz	23a$	USA,Mot,Rca	BDY29,MJ802,2N5886,2SD797
2N6259	Si-NPN	AF,Sw-Pow,170V,16A,250W,>0,2MHz	23a$	USA,Mot,Rca	BDW14,BDY56,2SC2607..08,2SD753..
2N626	Ge/Si-N-Darl	30/30/30V,B>18000	-	Sty	-
2N6260	Si-NPN	AF,Sw-Pow,50V,3A,29W,>0,8MHz	22a$	USA,Rca	BD241,BD535,BD935,2N4231..33..
2N6261	Si-NPN	AF,Sw-Pow,90V,4A,50W,>0,8MHz	22a$	USA,Rca	BD243B,BD539C,BD953,2N3054..
2N6262	Si-NPN	AF,Sw-Pow,170V,10A,150W,>0,8MHz	23a$	USA,Rca,Tix	BD745F,BDY54,2SC2607..08,2SD753..
2N6263	Si-NPN	AF,Sw-Pow,140V,3A,20W,>0,2MHz	22a$	USA,Rca	BD241D,BD243D,2N3441,2SD608..
2N6264	Si-NPN	AF,Sw-Pow,170V,3A,50W,>0,2MHz	22a$	-	BD241E,BD243E,2SD386(A)
2N6265	Si-NPN	UHF-Dr/Out,50V,0,275A,Pq>2W(2GHz)	62a&	Rca	-
2N6266	Si-NPN	UHF-Pow,50V,1A,Pq>5W(2GHz)	62a&	Rca	-
2N6267	Si-NPN	UHF-Pow,50V,1,5A,Pq>10W(2GHz)	62a&	Rca	-
2N6268	Si-NPN	UHF-Dr/Out,45V,0,35A,Pq>2W(2,3GHz)	62a&	Rca	-
2N6269	Si-NPN	UHF-Pow,45V,1,5A,Pq>6,5W(2,3GHz)	62a&	Rca	-
2N627	Ge-PNP	AF,Sw-Pow,40V,Ueb=20V,10A,94W	23a$	USA,Mot	AL100..101,AUY21,2N2288..93..
2N6270	Si-NPN	Sw,Pow,100V,30A,150W(Tc=100°),>75MHz	23a$	TI	2N5671,BUX10
2N6271	Si-NPN	=2N6270:120V	23a$	-	2N5671,BUX10
2N6272	Si-NPN	=2N6270:	49a$	-	2N2824..25
2N6273	Si-NPN	=2N6270:120V	49a$	-	2N2825,BUX10
2N6274	Si-NPN	Sw,Pow,120V,50A,250W,>30MHz	23a$	Mot,Ker,Ssi	2N6032..33
2N6275	Si-NPN	=2N6274:140V	23a$	-	2N6033,BUV20
2N6276	Si-NPN	=2N6274:160V	23a$	-	BUV21
2N6277	Si-NPN	=2N6274:180V	23a$	-	BUV21
2N6278	Si-NPN	=2N6274:	49a$	-	BUV20
2N6279	Si-NPN	=2N6274:140V	49a$	-	BUV20
2N628	Ge-PNP	=2N627:60V,Ueb=30V	23a$	USA,Mot	AL100..101,AUY21,2N2292..93..
2N6280	Si-NPN	=2N6274:160V	49a$	-	BUV20
2N6281	Si-NPN	=2N6274:180V	49a$	-	BUV21
2N6282	Si-N-Darl+Di	AF,Sw-Pow,60V,20A,160V,B>750	23a$	USA,Lbd,Mot	BDX69(A..C),MJ11012,2SD730,2SD1460
2N6283	Si-N-Darl+Di	=2N6282:80V	23a$	-	BDX69A..C,MJ11014,2SD730,2SD1460
2N6284	Si-N-Darl+Di	=2N6282:100V	23a$	-	BDX69B..C,MJ11016,2SD730,2SD1460
2N6285	Si-P-Darl+Di	AF,Sw-Pow,60V,20A,160W,B>750	23a$	USA,Lbd,Mot	BDX68(A..C),MJ11011,2SB694
2N6286	Si-P-Darl+Di	=2N6285:80V	23a$	-	BDX68A..C,MJ11013,2N6287,2SB694
2N6287	Si-P-Darl+Di	=2N6285:100V	23a$	-	BDX68B..C,MJ11015,2SB694
2N6288	Si-NPN	AF,Sw-Pow,40V,7A,40W,>4MHz	17j$	Fer,Mic,Mot	BD243,BD543,BD795,BD805,+
2N6289	Si-NPN	=2N6288	17j$	-	BD243B,BD543,BD795,BD805..
2N629	Ge-PNP	=2N627:80V,Ueb=40V	23a$	USA,Mot	AL100..101,AUY37,2N2292..93..
2N6290	Si-NPN	=2N6288:60V	17j$	-	BD243B,BD543A,BD797,BD807..
2N6291	Si-NPN	=2N6288:60V	17j$	-	BD243B,BD543A,BD797,BD807..
2N6292	Si-NPN	=2N6288:80V	17j$	-	BD243B,BD543B,BD799,BD809..
2N6293	Si-NPN	=2N6288:80V	17j$	-	BD243B,BD543B,BD799,BD809..
2N6294	Si-N-Darl+Di	AF,Sw-Pow,60V,4A,50W,B>750	22a$	Mot,Stc	BD645,BD897,BDW23A,BDW63A..
2N6295	Si-N-Darl+Di	=2N6294,80V	22a$	-	BD647,BD899,BDW23B,BDW63B..
2N6296	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,50W,B>750	22a$	Mot,Stc	BD646,BD898,BDW24A,BDW64A..
2N6297	Si-P-Darl+Di	=2N6296:80V	22a$	-	BD648,BD900,BDW24B,BDW64B..
2N6298	Si-P-Darl+Di	=2N6053:75W	22a$	Mot,Stc	BD646,BD898,BDW74A,BDX54A..
2N6299	Si-P-Darl+Di	=2N6054:75W	22a$	Mot,Stc	BD648,BD900,BDW74B,BDX54B..
2N63	Ge-PNP	AF,25V,Ueb=12V,0,02A,0,1W,0,6MHz	?1a	USA	AC125..126,AC151
2N630	Ge-PNP	=2N627:100V,Ueb=50V	23a$	USA,Mot	AL100..101,AUY37,2N2290,2N2293..

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2N6300	Si-N-Darl+Di	=2N6055:75W	22a$	Mot,Stc	BD645,BD897,BDW73A,BDX53A..
2N6301	Si-N-Darl+Di	=2N6056:75W	22a$	Mot,Stc	BD647,BD899,BDW73B,BDX53B..
2N6302	Si-NPN	Sw,Pow,140V,16A,150W,>0,2MHz	23a$	Ker,Stc,Tix	BD745E,BDX50,2N3773,2SC2608
2N6303	Si-PNP	Sw,80V,3A,1W,>60MHz,<100/400nS	2a$	USA,Mot,Sgs	-
2N6304	Si-NPN	UHF,30V,0,05A,0,2W,>1400MHz	5g	Mot,Sca	BFS55,BFR37,BFW30,BFX73..
2N6305	Si-NPN	UHF,30V,0,05A,0,2W,>1200MHz	5g	Mot,Sca	BFS55,BFR37,BFW30,BFX73..
2N6306	Si-NPN	Sw,Pow,500/250V,8A,125W,>5MHz	23a$	USA,Mot,Rca	BUS12(A),BUW25..26,BUW34..36,+
2N6307	Si-NPN	=2N6306:600/300V	23a$	-	BUS12(A),BUW25..26,BUW35..36,BUY69A...
2N6308	Si-NPN	=2N6306:700/350V	23a$	-	BUS12(A),BUW26,BUW35..36,BUY69A...
2N6309	Si-NPN	Sw,Pow,120V,90A,400W,>30MHz	49a$	Mot	-
2N631	Ge-PNP	AF,25V,0,05A,0,167W,1,2MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6310	Si-NPN	=2N6309:140V	49a$	-	-
2N6311	Si-NPN	=2N6309:160V	49a$	-	-
2N6312	Si-PNP	AF,Sw-Pow,40V,5A,75W,>4MHz	22a$	USA,Mot	BD244,BDS40,BD948,2SB550..
2N6313	Si-PNP	=2N6312:60V	22a$	-	BD244A,BDS40A,BD950,2SB550..
2N6314	Si-PNP	=2N6312:80V	22a$	-	BD244B,BDS40B,BD952,2SB550..
2N6315	SI-NPN	=2N5873:90W	22a$	Mot,Ssi,Stc	BDS43A,BD797,BD807,2N5428..30..
2N6316	Si-NPN	=2N5874:90W	22a$	-	BDS43B,BD799,BD809,2N5428..30..
2N6317	Si-PNP	=2N5871:90W	22a$	-	BDS44A,BD798,BD808,2N5954..55..
2N6318	Si-PNP	=2N5872:90W	22a$	-	BDS44B,BD800,BD810,2N5954..
2N6319	Si-NPN	Sw,Pow,120/100V,80A,300W,>30MHz	-	Mot	-
2N632	Ge-PNP	AF,30V,0,05A,0,167W,1MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6320	Si-NPN	=2N6319:140/120V	-	Mot	-
2N6321	Si-NPN	=2N6319:160/140V	-	Mot	-
2N6322	Si-NPN	Sw,Pow,300/200V,30A,350W,>10MHz	23a$	TI	BUR21..22,BUV22..23,BUX22..23..
2N6323	Si-NPN	=2N6322:400/300V	23a$	-	BUV23,BUX23
2N6324	Si-NPN	=2N6322:	49a$	-	-
2N6325	Si-NPN	=2N6322:400/300V	49a$	-	-
2N6326	Si-NPN	AF,Sw-Pow,60V,30A,200W,>3MHz	23a$	USA,Tix	BDY29,MJ802,2N6270..72,2SD797
2N6327	Si-NPN	=2N6326:80V	23a$	-	BDY29,MJ802,2N6270..72,2SD797
2N6328	Si-NPN	=2N6326:100V	23a$	-	BDY29,MJ802,2N6270..72,2SD797
2N6329	Si-PNP	AF,Sw-Pow,60V,30A,200W,>3MHz	23a$	USA,Tix	2N5884,MJ4502
2N633	Ge-PNP	AF,35V,0,05A,0,167W,0,8MHz	2a	USA	AC125..126,AC151,2SB54,2SB56
2N6330	Si-PNP	=2N6329:80V	23a$	-	2N5884,MJ4502
2N6331	Si-PNP	=2N6329:100V	23a$	-	2N5884,MJ4502
2N6332	Thy-50Hz	30V,2A(Tc=80°),Igt/Ih<0,2/<5mA	2a$	Tag,Tix	TAG615-100,(C106Y,TAG106Y,..)
2N6333	Thy-50Hz	=2N6332:50V	2a$	-	TAG615-100,(C106F,TAG106F,..)
2N6334	Thy-50Hz	=2N6332:100V	2a$	-	TAG615-100,(C106A,TAG106A,..)
2N6335	Thy-50Hz	=2N6332:200V	2a$	-	TAG615-200,(C106B,TAG106B,..)
2N6336	Thy-50Hz	=2N6332:300V	2a$	-	TAG615-400,(C106C,TAG106C,..)
2N6337	Thy-50Hz	=2N6332:400V	2a$	-	TAG615-400,(C106D,TAG106D,..)
2N6338	Si-NPN	Sw,Pow,120V,25A,200W,>40MHz	23a$	USA,Mot,Tix	BDW30,BUX10,2N5671..72,2N6272,2N6274..77
2N6339	Si-NPN	=2N6338:140V	23a$	-	BDW30,BDY58,BUX10,2N5672,2N6275..77
2N6340	Si-NPN	=2N6338:160V	23a$	-	BDW32,BDY58,2N6276..77
2N6341	Si-NPN	=2N6338:180V	23a$	-	BDW34,2N6277
2N6342	Triac	200V,8A(Tc=80°),Igt/Ih<50/<40mA	17h$	Mot,Rca,Tag	T2802B,MAC222-4,TIC226B,TXD10K40..
2N6342A	Triac	=2N6342:12A(Tc=80°)	17h$	-	TIC236B,TW11N400,TXD10K40P,MAC15-4,..
2N6343	Triac	=2N6342:400V	17h$	-	T2802D,MAC222-6,TIC226D,TXD10K40..
2N6343A	Triac	=2N6343:12A(Tc=80°)	17h$	-	TIC236D,TW11N400,TXD10K40P,MAC15-6,..
2N6344	Triac	=2N6342:600V	17h$	-	T2802M,MAC222-8,TIC226M,TXD10K60..
2N6344A	Triac	=2N6344:12A(Tc=80°)	17h$	-	TIC236M,TW11N600,TXD10K60P,MAC15-8,..
2N6345	Triac	=2N6342:800V	17h$	-	T2802N,MAC222-10,TIC226N,TXD10K80..
2N6345A	Triac	=2N6345:12A(Tc=80°)	17h$	-	TIC236N,TW11N800,TXD10K80P,MAC15-10..
2N6346	Triac	200V,8A(Tc=80°),Igt/Ih<75/<40mA	17h$	Mot,Rca,Tix	TAG224-200,MAC222A-4,BT137/500..
2N6346A	Triac	=2N6346:12A(Tc=80°)	17h$	-	BT138/500,TAG255-200,TXD10H40P..
2N6347	Triac	=2N6346:400V	17h$	-	TAG224-400,MAC222A-6,BT137/500..
2N6347A	Triac	=2N6347:12A(Tc=80°)	17h$	-	BT138/500,TAG255-400,TXD10H40P..
2N6348	Triac	=2N6346:600V	17h$	-	TAG224-600,MAC222A-8,BT137/600..
2N6348A	Triac	=2N6348:12A(Tc=80°)	17h$	-	BT138/600,TAG255-600,TXD10H60P..
2N6349	Triac	=2N6346:800V	17h$	-	TAG224-800,MAC222A-10,BT137/800..
2N6349A	Triac	=2N6349:12A(Tc=80°)	17h$	-	BT138/800,TAG255-800,TXD10H80P..
2N635(A)	Ge-NPN	AF,Sw,20(A:25)V,0,3A,0,15W,12MHz	2a&	USA	ASY28..29,ASY73..75
2N6350	Si-NPN-Darl	Sw,80V,5A,5W(Tc=50°),B>2000	5t$	Amc,Stc,Uni	-

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2N6351	Si-NPN-Darl	Sw,150V,5A,5W(Tc=50°),B>1000	5t$	Amc,Stc,Uni	-
2N6352	Si-NPN-Darl	=2N6350:25W	22/3-Pin	Amc,Stc,Uni	-
2N6353	Si-NPN-Darl	=2N6351:25W	22/3-Pin	Amc,Stc,Uni	-
2N6354	Si-NPN	Sw,Pow,150/120V,10A,140W,>80MHz	23a$	USA,Rca,Sgs	BUX10
2N6355	Si-NPN-Darl	AF,Sw-Pow,50V,20A,150W,B>500	23a$	Ker,Mot,Stc..	BDX69(A..C),2N6059,2N6282..84,MJ11012..
2N6356	Si-NPN-Darl	=2N6355:B>1500	23a$	-	BDX69(A..C),2N6059,2N6282..84,MJ11012..
2N6357	Si-NPN-Darl	=2N6355:80V	23a$	-	BDX69A..C,2N6059,2N6283..84,MJ11014..
2N6358	Si-NPN-Darl	=2N6355:80V,B>1500	23a$	-	BDX69A..C,2N6059,2N6283..84,MJ11014..
2N6359	Si-NPN	AF,Sw-Pow,100V,16A,150W,>0,2MHz	23a$	USA,Tix	BD317,BDX40,2N3772,2N5629..31,2N5886...
2N6360	Si-NPN	=2N6359:120V	23a$	-	BDX50,2N3773,2N5630..31,2SC2608..
2N6361	Si-NPN	HF-Pow,60V,4A,50W	57s	Ctr,Mot	-
2N6362	Si-NPN	HF-Pow,60V,6A,110W	57s	Sol	-
2N6363	Si-NPN	HF-Pow,50V,10A,175W	57s	Ctr,Mot	-
2N6364	Si-NPN	HF-Pow,50V,10A,175W	57s	Ctr,Mot	-
2N6365(A)	Ge-PNP	HF,30V,0,1A,0,15W,500MHz	2a$	Mot	-
2N6366	Si-NPN	HF-Dr/Out,36V,1A,Pep=2,5W(30MHz)	49a$	Mot	(MRF476)
2N6367	Si-NPN	AM/SSB-Pow,36V,2A,Pep=9W(30MHz)	59r	Mot	MRF433
2N6368	Si-NPN	AM/SSB-Pow,40V,8A,Pep=40W(30MHz)	59r	Mot	MRF460
2N6369	Si-NPN	HF-Pow,60V,15A,220W	57s	Mot	-
2N637	Ge-PNP	AF,Sw-Pow,-/40V,5A,60W,0,5MHz	23a$	USA	AL102..103,AUY28,2N1545..48..
2N6370	Si-NPN	AM/SSB-Pow,65V,1,5A,Pep=10W(30MHz)	59r	Mot	MRF433
2N6371	Si-NPN	AF,Sw-Pow,50V,5A,150W,>0,8MHz	23a$	USA,Rca,Tix	BD315,BDX40,2N3055,2N3772,2N5629..31..
2N6372	Si-NPN	AF,Sw-Pow,90V,6A,40W,>4MHz	22a$	Rca,Ssi,Stc	BD243C,BD543C,BD801,2N5429..30..
2N6373	Si-NPN	=2N6372:70V	22a$	-	BD243B,BD543B,BD799,2N5427..30..
2N6374	Si-NPN	=2N6372:50V	22a$	-	BD243A,BD543A,BD797,2N5427..30..
2N6375	Si-NPN	Sw,75V,1,5A,0,58W,<16/45nS	2a$	Nsc	2N3737
2N6376	Si-NPN	=2N6375:1W	2a$	-	BSS14,2N3735,2N5262,2N5859..61
2N6377	Si-PNP	Sw,Pow,100V,50A,250W,>30MHz	23a$	Ker,Mot,Stc	-
2N6378	Si-PNP	=2N6377:120V	23a$	-	-
2N6379	Si-PNP	=2N6377:140V	23a$	-	-
2N637A	Ge-PNP	=2N637:-/70V	23a$	-	AL102..103,AUY28,2N1546..48..
2N637B	Ge-PNP	=2N637:-/80V	23a$	-	AL102..103,AUY28,2N1547..48..
2N638	Ge-PNP	AF,Sw-Pow,-/40V,5A,60W,0,5MHz	23a$	USA	AL102..103,AUY28,2N1545..48..
2N6380	Si-PNP	=2N6377:	49a$	-	-
2N6381	Si-PNP	=2N6377:120V	49a$	-	-
2N6382	Si-PNP	=2N6377:140V	49a$	-	-
2N6383	Si-N-Darl+Di	AF,Sw-Pow,40V,10A,100W,>20MHz	23a$	Fch,Fer,Lbd	BDV67,BDW83,BDX83,BDX85..
2N6384	Si-N-Darl+Di	=2N6383:60V	23a$	-	BDV67,BDW83A,BDX83A,BDX85A,BDX87C...
2N6385	Si-N-Darl+Di	=2N6383:80V	23a$	-	BDV67A,BDW83B,BDX83B,BDX85B,MJ3001...
2N6386	Si-N-Darl+Di	AF,Sw-Pow,40V,8A,65W,B>1000	17j$	Fch,Mot,Nsc	BD643,BD895,BDW73,BDX53..
2N6387	Si-N-Darl+Di	=2N6386:60V,10A	17j$	-	BD645,BD897,BDW73A,BDX53A..
2N6388	Si-N-Darl+Di	=2N6386:80V,10A	17j$	-	BD647,BD899,BDW73B,BDX53B..
2N6389	Si-NPN	UHF,20V,0,04A,0,2W,>1GHz	5g	Rca,Sca	BF377..378,BFR37,BFW30,BFX73..
2N638A	Ge-PNP	=2N638:-/70V	23a$	-	AL102..103,AUY28,2N1546..48..
2N638B	Ge-PNP	=2N638:-/80V	23a$	-	AL102..103,AUY28,2N1547..48..
2N639	Ge-PNP	AF,Sw-Pow,-/40V,5A,60W,0,5MHz	23a$	USA	AL102..103,AUY28,2N1545..48..
2N6390	Si-NPN	HF-Pow,50V,1A,8,3W	62a&	Rca	-
2N6391	Si-NPN	HF-Pow,50V,2,5A,16W	62a&	Rca	-
2N6392	Si-NPN	HF-Pow,50V,3,5A,21W	62a&	Rca	-
2N6393	Si-NPN	HF-Pow,45V,3,5A,21W	62a&	Rca	-
2N6394	Thy-50Hz	50V,12A(Tc=90°),Igt/Ih<30/<40mA	17h$	Mot,Rca,Tag	TAG665-100,TIC126F,T7,5N400,2N6400,..
2N6395	Thy-50Hz	=2N6394:100V	17h$	-	TAG665-100,TIC126A,T7,5N400,2N6401,..
2N6396	Thy-50Hz	=2N6394:200V	17h$	-	TAG665-200,TIC126B,T7,5N400,2N6402,..
2N6397	Thy-50Hz	=2N6394:400V	17h$	-	TAG665-400,TIC126D,T7,5N400,2N6403,..
2N6398	Thy-50Hz	=2N6394:600V	17h$	-	TAG665-600,TIC126M,T7,5N600,2N6404,..
2N6399	Thy-50Hz	=2N6394:800V	17h$	-	TAG665-800,TIC126N,T7,5N800,2N6405,..
2N639A	Ge-PNP	=2N639:-/70V	23a$	-	AL102..103,AUY28,2N1546..48..
2N639B	Ge-PNP	=2N639:-/80V	23a$	-	AL102..103,AUY28,2N1547..48..
2N64	Ge-PNP	AF,25V,Ueb=12V,0,02A,0,1W,0,8MHz	?1a	USA	AC125..126,AC151
2N640	Ge-PNP	HF,34V,10mA,0,08W,42MHz	1g	Rca,Sty	AF124..126,AF200
2N6400	Thy-50Hz	50V,16A(Tc=90°),Igt/Ih<30/<40mA	17h$	Mot,Rca,Tag	TAG680-100,TAG681-100,T9,5N400..
2N6401	Thy-50Hz	=2N6400:100V	17h$	-	TAG680-100,TAG681-100,T9,5N400..
2N6402	Thy-50Hz	=2N6400:200V	17h$	-	TAG680-200,TAG681-200,T9,5N400..

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2N6403	Thy-50Hz	=2N6400: 400V	17h$	-	TAG680-400,TAG681-400,T9,5N400..
2N6404	Thy-50Hz	=2N6400: 600V	17h$	-	TAG680-600,TAG681-600,T9,5N600..
2N6405	Thy-50Hz	=2N6400: 800V	17h$	-	TAG680-800,TAG681-800,T9,5N800..
2N6406	Si-PNP	AF,Sw-Pow,80V,2A,12,5W,>50MHz	14j$	Mot	MJE172
2N6407	Si-PNP	=2N6407: 100V	14j$	-	MJE172
2N6408	Si-NPN	AF,Sw-Pow,80V,2A,12,5W,>50MHz	14j$	Mot	MJE182
2N6409	Si-NPN	=2N6408: 100V	14j$	-	MJE182
2N641	Ge-PNP	HF,34V,10mA,0,08W,42MHz	1g	Rca,Sty	AF124..126,AF200
2N6410	Si-NPN	AF,Sw-Pow,40V,4A,15W,>50MHz	14j$	Mot	BD435
2N6411	Si-PNP	AF,Sw-Pow,40V,4A,15W,>50MHz	14j$	Mot	MJE210
2N6412	Si-NPN	AF,Sw-Pow,60V,4A,15W,>50MHz	14j$	Mot	MJE182
2N6413	Si-NPN	=2N6412: 80V	14j$	-	MJE182
2N6414	Si-PNP	AF,Sw-Pow,60V,4A,15W,>50MHz	14j$	Mot	MJE172
2N6415	Si-PNP	=2N6414: 80V	14j$	-	MJE172
2N6416	Si-NPN	AF,Sw-Pow,80V,3A,15W,>40MHz	14j$	Mot	(BD787,BD789,MJE240..244,..)
2N6417	Si-NPN	=2N6416: 100V	14j$	-	(BD791,BDX35..37,MJE243..244,..)
2N6418	Si-PNP	AF,Sw-Pow,80V,3A,15W,>40MHz	14j$	Mot	(BD788,BD790,MJE250..254,..)
2N6419	Si-PNP	=2N6418: 100V	14j$	-	(BD792,MJE253..254)
2N642	Ge-PNP	HF,34V,10mA,0,08W,42MHz	1g	Rca,Sty	AF124..126,AF200
2N6420	Si-PNP	Sw,Pow,250/175V,1A,35W,>10MHz	22a$	Mot,Rca	BUX66A..C,2N5344..45,2SA1009(A)..
2N6421	Si-PNP	Sw,Pow,375/250V,1A,35W,>10MHz	22a$	Mot,Rca	BUX66C,2N6213..14,2SA1009A..
2N6422	Si-PNP	Sw,Pow,500/300V,2A,35W,>10MHz	22a$	Mot,Rca	-
2N6423	Si-PNP	Sw,Pow,500/300V,2A,35W,>15MHz	22a$	Mot,Rca	-
2N6424	Si-PNP	Sw,Pow,250/225V,1A,20W,>10MHz	22a$	Mot	BUX66A..C,2N5344..45,2SA1009(A)..
2N6425	SI-PNP	Sw,Pow,325/300V,1A,20W,>10MHz	22a$	Mot	BUX66B..C,2N6212..14,2SA1009(A)..
2N6426	Si-NPN-Darl	GenP,40V,0,5A,0,625W,B>20000	7e	Mot,Nsc,Spr	BC517,BC617,MPSA25..29,2SD892A..
2N6427	Si-NPN-Darl	GenP,40V,0,5A,0,625W,B>10000	7e	-	BC517,BC617,MPSA25..29,2SD892A..
2N6428(A)	Si-NPN	GenP,60V,0,2A,0,625W,>100MHz	7e	Mot	BC414,BC550,2SC1775(A),2SC2390..
2N6429(A)	Si-NPN	GenP,55V,0,2A,0,625W,>700MHz	7e	-	BC414,BC550,2SC1775(A),2SC2390..
2N643	Ge-PNP	HF/Sw,30V,0,1A,0,12W,30MHz,<90/86nS	2a	Rca,Sty	2N2955..57
2N6430	Si-NPN	Vid,200V,0,5A,0,5W,>50MHz	2a$	Mot	BF391..393,BFP22,MPSA42..43..
2N6431	Si-NPN	=2N6430: 300V	2a$	-	BF393,BFP25,MPSA42,2SD1350
2N6432	Si-PNP	Vid,200V,0,5A,0,5W,>50MHz	2a$	Mot	BF491..493,BFP23,MPSA92..93..
2N6433	Si-PNP	=2N6432: 300V	2a$	-	BF493,BFP26,MPSA92,2SB1074
2N6436	Si-PNP	Sw,Pow,100V,25A,200W,>40MHz	23a$	Ker,Mot,Stc	2N6377..79
2N6437	Si-PNP	=2N6436: 120V	23a$	-	2N6378..79
2N6438	Si-PNP	=2N6436: 140V	23a$	-	2N6379
2N6439	Si-NPN	VHF/UHF-Pow,60V,Pq=60W(400MHz)	57s	Mot	MRF327,2SC2186,2SC2796
2N644	Ge-PNP	HF/Sw,30V,0,1A,0,12W,50MHz,<68/64nS	2a	Rca,Sty	2N2955..57
2N6441	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	Mot,Isi	2N3409..11
2N6442	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6443	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6444	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6445	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6446	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6447	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6448	Si-NPN	Dual,60V,0,01A,0,55W,>160MHz	81bs	-	2N3409..11
2N6449	N-FET	GenP,300V,Idss>2mA,Up<15V	2b&	Tdy,Tix	-
2N645	Ge-PNP	HF/Sw,30V,0,1A,0,12W,75MHz,<46/42nS	2a	Rca,Sty	2N2955..57
2N6450	N-FET	GenP,200V,Idss>2mA,Up<15V	2b&	Tdy,Tix	-
2N6451	N-FET	GenP,LN,20V,Idss>5mA,Up<3,5V	5h+	TI	BC264,BF410C,2SK147,2SK168
2N6452	N-FET	GenP,LN,25V,Idss>5mA,Up<3,5V	5h+	TI	BC264,BF410C,2SK147,2SK168
2N6453	N-FET	GenP,LN,20V,Idss>15mA,Up<5V	5h+	TI	BF256B,BF348,BFT10A,B,2N5397
2N6454	N-FET	GenP,LN,25V,Idss>15mA,Up<5V	5h+	TI	BF256B,BF348,BFT10A,B,2N5397
2N6455	Si-NPN	HF-Pow,45V,7A,60W,>75MHz	55r	Ppc	-
2N6456	Si-NPN	HF-Pow,45V,12A,75W,>60MHz	55r	Ppc	-
2N6457	Si-NPN	HF-Pow,45V,20A,140W,>50MHz	55r	Ppc	-
2N6458	Si-NPN	HF-Pow,45V,7A,75W,>75MHz	59r	Ppc	-
2N6459	Si-NPN	HF-Pow,45V,12A,120W,>60MHz	59r	Ppc	-
2N646	Ge-NPN	AF,Sw,25V,Ueb=12V,0,05A,0,1W	1a	Sty	AC127,ASY28..29
2N6460	Si-NPN	HF-Pow,45V,20A,140W,>50MHz	59r	Ppc	-
2N6461	Si-NPN	Vid,300V,0,1A,1W,>200MHz,B>30	2a$	Ssi,Tix	BF259,BF659,BFS89,3N5058
2N6462	Si-NPN	=2N6461: B>100	2a$	-	BF259,BF659,BFS89,3N5058
2N6463	Si-NPN	=2N6461: 250V	2a$	-	BF258..259,BF658..659,2N5058..59..

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2N6464	Si-NPN	=2N6461: 250V, B>100	2a$	-	BF258..259, BF658..659, 2N5058..59..
2N6465	Si-NPN	AF, Sw-Pow, 110V, 4A, 40W, >5MHz	22a$	Ker,Stc,Stc	BD243C, BD539D, BD955, 2SD961..
2N6466	Si-NPN	=2N6465: 130V	22a$	-	BD243D, 2SC2516, 2SD961
2N6467	Si-PNP	AF, Sw-Pow, 110V, 4A, 40W, >5MHz	22a$	Ker,Rca,Stc	BD244C, BD540D, BD956, 2SB869..
2N6468	Si-PNP	=2N6467: 130V	22a$	-	BD244D, 2SB869
2N6469	Si-PNP	AF, Sw-Pow, 50V, 15A, 125W, >10MHz	23a$	USA,Rca,Tix	BD316, BD546A, BDW52C, MJ2955, 2N5879..80..
2N647(/22)	Ge-NPN	AF, Sw, 25V, Ueb=12V, 0,05A	2a	Csr,Etc,Syl	AC127, ASY28..29
2N6470	Si-NPN	AF, Sw-Pow, 50V, 15A, 125W, >5MHz	23a$	USA,Rca,Tix	BD315, BD545A, BDW51C, 2N3055, 2N5881..82..
2N6471	Si-NPN	=2N6470: 70V	23a$	-	BD315, BD545B,, BDW51C2N3055, 2N5881..82..
2N6472	Si-NPN	=2N6470: 90V	23a$	-	BD317, BD545C,, BDW51C2N3055, 2N5882..
2N6473	Si-NPN	=2N6465:	17j$	USA,Nsc,Rca	2N6465, BD711
2N6474	Si-NPN	=2N6466:	17j$	USA,Nsc,Rca	→2N6466
2N6475	Si-PNP	=2N6467:	17j$	USA,Nsc,Rca	2N6467, BD912
2N6476	Si-PNP	=2N6468:	17j$	USA,Nsc,Rca	→2N6468
2N6477	Si-NPN	AF, Sw-Pow, 140V, 2,5A, 50W, >0,2MHz	17j$	Rca	BD241D, BD941, 2SC2516
2N6478(A)	Si-NPN	=2N6477>160V	17j$	-	BD241D
2N6479	Si-NPN	Sw, Pow, RadH, 100/60V, 12A, 87W, >100MHz	-	Rca	-
2N6480	Si-NPN	=2N6479: RadH, 100/80V	-	Rca	-
2N6481	Si-NPN	=2N6479: RadH, 117W	-	Rca	-
2N6482	Si-NPN	=2N6479: RadH, 100/80V, 117W	-	Rca	-
2N6483	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	81bx	Isi,Nsc,Sol	-
2N6484	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	81bx	-	-
2N6485	N-FET	Dual, 50V, Idss>0,5mA, Up<4V	81bx	-	-
2N6486	Si-NPN	AF, Sw-Pow, 50V, 15A, 75W, >5MMHz	17j$	Fch,Mot,Nsc	BD743A, BD907, BDT81
2N6487	Si-NPN	=2N6486: 70V	17j$	-	BD743B, BD909, BDT83
2N6488	Si-NPN	=2N6486: 90V	17j$	-	BD743C, BD911, BDT85
2N6489	Si-PNP	AF, Sw-Pow, 50V, 15A, 75W, >5MHz	17j$	=2N6486	BD744A, BD908, BDT82
2N649(/5,/22)	Ge-NPN	AF, Sw, 20V, 0,05A, 0,1(/22:0,18)W	2a	USA	AC127, ASY28..29
2N6490	Si-PNP	=2N6489: 70V	17j$	-	BD744B, BD910, BDT84
2N6491	Si-PNP	=2N6489: 90V	17j$	-	BD744C, BD912, BDT86
2N6492	Si-NPN-Darl	AF, Sw-Pow, 55V, 15A, 100W, B>500	23a$	Mot	BDV67, BDW83A, BDX67, MJ4033..
2N6493	Si-NPN-Darl	AF, Sw-Pow, 100V, 15A, 100W, B>500	23a$	Mot	BDV67A, BDW83C, BDX67B, MJ4035..
2N6494	Si-NPN-Darl	AF, Sw-Pow, 100V, 15A, 100W, B>500	23a$	Mot	BDV67A, BDW83C, BDX67B, MJ4035..
2N6495	Si-NPN	Sw, Pow, 150V, 10A, 70W, >25MHz	22a$	USA,Mot,Tix	BUS36..37, BUV27(A), 2SC2867
2N6496	Si-NPN	Sw, Pow, 150V, 15A, 140W, >60MHz	23a$	Ker,Rcs,Sgs	BUW57..58, BUX41, 2SD552, 2SD583,+
2N6497	Si-NPN	AF, Sw-Pow, 350/250V, 5A, 80W, >5MHz	17j$	Mot,Sgs	BUT56(A), MJE51T..53T, 2SC2907..
2N6498	Si-NPN	=2N6497: 400/300V	17j$	-	BUT56(A), MJE52T..53T, 2SC2907..
2N6499	Si-NPN	=2N6497: 450/350V	17j$	-	BUT56(A), MJE53T, ST13005, 2SC3056...
2N65	Ge-PNP	AF, 25V, Ueb=16V, 0,02A, 0,125W, 1MHz	71a	USA	AC125..126, AC151
2N650(A)	Ge-PNP	AF, Sw, 45V, Ueb=30V, 0,5A, 0,2W, B>33	2a	USA,Mot	2N1189..90, 2SB405ST
2N6500	Si-NPN	Sw, Pow, 120V, 4A, 35W, >60MHz	22a$	USA,Rca,Tix	BDV10..12, BUX77, 2SC2767, 2SD772..
2N6501	Si-NPN	4xNPN, 80V, 1A, 0,6W, >250MHz	14-FLP/cs	Mot	-
2N6502	Si-NPN	Dual, 80V, 1A, 0,6W, >250MHz	81bs	Mot,Sgs	-
2N6503	Si-NPN	Dual, 80V, 1A, 0,35W, >250MHz	10-FLP/ch	Mot,Sgs	-
2N6504	Thy-SOHz	50V, 25A, Igt/Ih<40/<40mA	17h$	Mot	MCR69-2
2N6505	Thy-SOHz	=2N6504: 100V	17h$	-	MCR69-3
2N6506	Thy-SOHz	=2N6504: 200V	17h$	-	-
2N6507	Thy-SOHz	=2N6504: 400V	17h$	-	-
2N6508	Thy-SOHz	=2N6504: 600V	17h$	-	-
2N6509	Thy-SOHz	=2N6504: 800V	17h$	-	-
2N651(A)	Ge-PNP	=2N650: B>45	2a	USA,Mot	2N1189..90, 2SB405ST
2N6510	Si-NPN	Sw, Pow, 250/200V, 7A, 120W, >3MHz	23a$	RCA	BUX18(A..C), BUX43..44, 2SC3041..
2N6511	Si-NPN	=2N6510: 300/250V	23a$	-	BUX18(A..C), BUX43..44, BUX80, 2SC3041..
2N6512	Si-NPN	=2N6510: 350/300V	23a$	-	BUX18A..C, BUX43..44, BUX80, 2SC3041..
2N6513	Si-NPN	=2N6510: 400/350V	23a$	-	BUX18B..C, BUX43..44, BUX80, 2SC3041..
2N6514	Si-NPN	=2N6510: 350/300V	23a$	-	BUX18A..C, BUX43..44, BUX80, 2SC3041..
2N6515	Si-NPN	AF, Sw-Vid, 250V, 0,5A, 0,625W, >40MHz	7e	Mot,Sam	BF392..393, BFP25, MPSA42, 2SD1350
2N6516	Si-NPN	=2N6515: 300V	7e	Mot,Sam	BF393, BFP25, MPSA42, 2SD1350
2N6517	Si-NPN	=2N6515: 350V	7e	Mot,Sam,Ztx	2SD1350
2N6518	Si-PNP	AF/Sw-Vid, 250V, 0,5A, 0,625W, >40MHz	7e	Mot,Sam	BF492..493, BFP26, MPSA92, 2SB1074
2N6519	Si-PNP	=2N6518: 300V	7e	Mot,Sam	BF493, BFP26, MPSA92, 2SB1074
2N652(A)	Ge-PNP	=2N650: B>80	2a	USA,Mot	2N1189..90, 2SB405ST
2N6520	Si-PNP	=2N6518: 350V	7e	Mot,Sam,Ztx	BF493S, 2SB1074
2N6521	Si-PNP-Darl	60V, 1A, 0,7W, B>10000	5r	Mot	-

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2N6522	Si-PNP-Darl	=2N6521:B>20000	Sr	-	-
2N6523	Si-NPN	HF-Pow,40V,0,6A,5W	62a&	Mws	-
2N6524	Si-NPN	HF-Pow,40V,1,2A,10W	62a&	Mws	-
2N6525	Si-NPN	HF-Pow,40V,2,5A,20W	62a&	Mws	-
2N6526	Si-NPN	HF-Pow,50V,0,5A,3,9W	62a&	Mws	-
2N6527	Si-NPN	HF-Pow,50V,1A,5W	62a&	Mws	-
2N6528	Si-NPN	HF-Pow,50V,1,2A,10W	62a&	Mws	-
2N6529	Si-NPN	HF-Pow,50V,2,5A,20W	62a&	Mws	-
2N653	Ge-PNP	AF,Sw,30V,Ueb=25V,0,25A,0,2W,a>30	2a	USA,Mot	AC125..126,AC151
2N6530	Si-N-Darl+Di	AF,Sw-Pow,80V,8A,65W,B>1000	17j$	Rca	BD647,BD899,BDX53B,BDX73B,TIP102...
2N6531	Si-N-Darl+Di	AF,Sw-Pow,100V,8A,65W,B>500	17j$	Rca	BD649,BD901,BDX53C,BDX73C..
2N6532	Si-N-Darl+Di	AF,Sw-Pow,100V,8A,65W,B>1000	17j$	Rca	BD649,BD901,BDX53C,BDX73C..
2N6533	Si-N-Darl+Di	AF,Sw-Pow,120V,8A,65W,B>1000	17j$	Rca	BD651,BDT21,BDX53D,BDX73D..
2N6534	Si-N-Darl+Di	=2N6530:36W	22a$	Rca	→2N6530
2N6535	Si-N-Darl+Di	=2N6531:36W	22a$	Rca	2N6531,TIP102
2N6536	Si-N-Darl+Di	=2N6532:36W	22a$	Rca	→2N6532
2N6537	Si-N-Darl+Di	=2N6533:36W	22a$	Rca	→2N6532
2N6538	Si-NPN	GenP,LN,60V,0,2A,0,625W,>200MHz	7e	TI	BC414,BC550,2SC2240,2SC2459..
2N6539	Si-NPN	GenP,LN,60V,0,2A,0,625W,>200MHz	7e	-	BC414,BC550,2SC2240,2SC2459..
2N654	Ge-PNP	=2N653:a>50	2a	USA,Mot	AC125..126,AC151
2N6540	Si-NPN	GenP,LN,80V,0,2A,0,625W,>200MHz	7e	-	2SC1775(A),2SC2240,2SC2459,2SC2390,..
2N6541	Si-NPN	GenP,LN,80V,0,2A,0,625W,>200MHz	7e	-	2SC1775(A),2SC2240,2SC2459,2SC2390,..
2N6542	Si-NPN	Sw,Pow,650/300V,5A,100W,>6MHz	23a$	USA,Mot,Rca	BUS11(A),BUX82..83,2SC3048..
2N6543	Si-NPN	=2N6542:850/400V	23a$	-	BUS11(A),BUX82..83,2SC3048..
2N6544	Si-NPN	Sw,Pow,650/300V,8A,125W,>6MHz	23a$	=2N6542	BUS12(A),BUX47(A),2SC3092,2SD811,..
2N6545	Si-NPN	=2N6544:850/400V	23a$	-	BUS12(A),BUX47(A),BUX80,2SC3092,2SD811,..
2N6546	Si-NPN	Sw,Pow,650/300V,15A,175W,>6MHz	23a$	=2N6542	2N6547,BUS13(A),BUS97(A),BUX47(A..C)..
2N6547	Si-NPN	=2N6546:850/400V	23a$	-	BUS13(A),BUS97(A),BUX47(A..C)..
2N6548	Si-NPN-Darl	AF,Sw-Pow,50V,2A,10W,B>25000	13g$	Motorola	BD411..412,MJE802,MPSU45
2N6549	Si-NPN-Darl	=2N6548:B>15000	13g$	-	BD411..412,MJE802,MPSU45
2N655	Ge-PNP	=2N653:a>100	2a	USA,Mot	AC125..126,AC151
2N6550	N-FET	GenP,20V,Idss=10..250mA,Up<3V	2f&	Tdy	-
2N6551	Si-NPN	AF,Sw-Pow,60V,1A,10W,>75MHz	13g$	Motorola	BD237,BC366,BD415,BD517,BD525..
2N6552	Si-NPN	=2N6551:80V	13g$	-	BD237,BC367,BD417,BD519,BD527..
2N6553	Si-NPN	=2N6551:100V	13G$	-	BD237,BD419,BD529
2N6554	Si-PNP	AF,Sw-Pow,60V,1A,10W,>75MHz	13g$	Motorola	BD238,BC363,BD416,BD518,BD526..
2N6555	Si-PNP	=2N6554:80V	13g$	-	BC364,BD418,BD520,BD528..
2N6556	Si-PNP	=2N6554:100V	13g$	-	BD238,BD420,BD530
2N6557	Si-NPN	Vid-Pow,250V,0,5A,10W,>45MHz	13g$	Motorola	BF381..382,BF460..462,MJE340,MPSU10
2N6558	Si-NPN	=2N6557:300V	13g$	-	BF382,BF461..462,BF468,MJE340,MPSU10
2N6559	Si-NPN	=2N6557:350V	13g$	-	BF462,MJE340
2N656(A,S)	Ge-PNP	AF,Sw,60V,0,5A,1W	2a$	USA,Mot,Tix	BC140..141,BC300..302,2N3053..
2N6560	Si-NPN	Sw,Pow,450/450V,10A,220W,>10MHz	23a$	Sol,Stc	-
2N6561	Si-NPN	=2N6560:300/300V	23a$	-	-
2N6562	Si-NPN	=2N6560:175W	49a	-	2N6689..93
2N6563	Si-NPN	=2N6560:300/300V,175W	49a	-	2N6689..93
2N6564	Thy-50Hz	300V,0,5A(Tc=55°),Igt/Ih<0,2/<5mA	7e	Gen,Tag	2N5064,TAG72D,TAG59D,2N6683..
2N6565	Thy-50Hz	=2N6564:400V	7e	-	TAG72D,TAG59D,2N6683,(BT149D,..)
2N6566	Si-NPN	Sw,Chopper,30/30/30V,0,1A,0,4W	2a$	Tdy	-
2N6567	Si-PNP	Sw,Chopper,30/30/30V,0,1A,0,4W	2a$	Tdy	-
2N6568	N-FET	GenP,30V,Idss>500mA,Up<10V	2b&	Tdy	-
2N6569	Si-NPN	AF,Sw-Pow,45V,12A,100W,>1,5MHz	23a$	Fch,Mot,Rca	BD315,BD545A,BDW51,2N5881..82,+
2N657(A,S)	Ge-PNP	=2N656:100V	2a$	USA,Mot,Tix	BC141,BC300,2N1889..90,2N1990..
2N6570	Si-NPN	AF,Sw-Pow,100V,40A,250W,>1MHz	23a$	Stc,Trw	2N6032..33,2N6274..77
2N6571	Si-NPN	=2N6570:115V	23a$	-	2N6032..33,2N6274..77
2N6572	Si-NPN	HF-Pow,60V,12A,250W	57s	Ctr	-
2N6573	Si-NPN	Sw,Pow,500/250V,10A,125W,15MHz	23a$	USA,Mot,Tho	BUW25..26,BUW34..36,2N6547,2SC3046..
2N6574	Si-NPN	=2N6573:600/275V	23a$	-	BUW25..26,BUW35..36,2SC3046..
2N6575	Si-NPN	=2N6573:700/300V	23a$	-	BUS12(A),BUW26,BUW35..36,BUX48,2SC3046..
2N6576	Si-N-Darl+Di	AF,Sw-Pow,60V,15A,120W,B>500	23a$	Lbd,Mot,Rca	BDV67,BDW83A,BDX67,MJ4033..
2N6577	Si-N-Darl+Di	=2N6576:90V	23a$	-	BDV67A,BDW83C,BDX67B,MJ4035..
2N6578	Si-N-Darl+Di	=2N6576:120V	23a$	-	BDV67B,BDW83D,BDX67C
2N6579	Si-NPN	Sw,Pow,450/350V,10A,125W,>25MHz	23a$	AMC	BUW24..26,BUW34..36,2SC3046..
2N658	Ge-PNP	AF,Sw,25/16/12V,1A,0,2W,5MHz	2a$	USA	AC128,AC153,AC188,2SB405..

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2N6580	Si-NPN	Sw,Pow,500/400V,10A,125W,>25MHz	23a$	-	BUW25..26,BUW34..36,2SC3046..
2N6581	Si-NPN	Sw,Pow,550/450V,10A,125W,>25MHz	23a$	-	BUW25..26,BUW35..36,2SC3046..
2N6582	Si-NPN	Sw,Pow,450/350V,10A,125W,>25MHz	23a$	AMC	BUW24..26,BUW34..36,2SC3046..
2N6583	Si-NPN	Sw,Pow,500/400V,10A,125W,>25MHz	23a$	-	BUW25..26,BUW34..36,2SC3046..
2N6584	Si-NPN	Sw,Pow,550/450V,10A,125W,>25MHz	23a$	-	BUW25..26,BUW35..36,2SC3046..
2N6585	Si-NPN	=2N6579:	49a	-	2N6689..93
2N6586	Si-NPN	=2N6580:	49a	-	2N6690,2N6692..93
2N6587	Si-NPN	=2N6581:	49a	-	2N6690,2N6692..93
2N6588	Si-NPN	=2N6582:	49a	-	2N6689..93
2N6589	Si-NPN	=2N6583:	49a	-	2N6690,2N6692..93
2N659	Ge-PNP	AF,Sw,25/14/12V,1A,0,2W,10MHz	2a	USA	AC128,AC153,AC188,2SB405..
2N6590	Si-NPN	=2N6584:	49a	-	2N6690,2N6692..93
2N6591	Si-NPN	Sw,HA-Dr,Reg,150V,0,5A,10W,>35MHz	13g$	Motorola	BF380..382,BF460..462,MPSU10..
2N6592	Si-NPN	=2N6591:200V	13g$	-	BF381..382,BF460..462,MPSU10..
2N6593	Si-NPN	=2N6591:250V	13g$	-	BF381..382,BF460..462,MPSU10..
2N6594	Si-PNP	AF,Sw-Pow,45V,12A,100W,>2,5MHz	23a$	Mot,Rca	BD316,BD546A,BDW52,2N5879..80..
2N6595	Si-NPN	UHF,LN,20V,25mA,0,2W,>3,5GHz	5g	Amp	BFQ22,BFQ53,BFT66..67
2N6596	Si-NPN	UHF,LN,15V,25mA,0,2W,>3,5GHz	5g	Amp	BFQ22,BFQ53,BFT66..67
2N6597	Si-NPN	UHF,LN,20V,25mA,0,2W,>4GHz	5g	Amp	BFQ22,BFQ53,BFT66..67
2N6598	Si-NPN	UHF,LN,15V,25mA,0,2W,>4GHz	5g	Amp	BFQ22,BFQ53,BFT66..67
2N6599	Si-NPN	UHF,LN,20V,75mA,0,5W,>3GHz	5g	Amp	BFQ63,2SC2570,2SC3037,2SC3337
2N66	Ge-PNP	AF,Sw-Pow,60V,Ueb=60MHz,0,8A,27,5W	-	Wes	-
2N660	Ge-PNP	AF,Sw,25/11/12V,1A,0,2W,15MHz	2a	USA	AC128,AC153,AC188,2SB405..
2N6600	Si-NPN	UHF,LN,20V,75mA,0,3W,>3,5GHz	5g	Amp	BFQ63,2SC2570,2SC3037,2SC3337
2N6601	Si-NPN	UHF,LN,20V,50mA,0,25W,>1GHz	5g	Amp	BFQ63,BFS5S,2SC2498
2N6602	Si-NPN	UHF,-/15V,25mA,>3,5GHz	52r	Mot	BFQ59..60,BFQ72,BFT65,2SC2844..
2N6603	Si-NPN	UHF,25V,30mA,>3,5GHz	52r	Mot	BFQ59..60,BFQ72,BFT65,2SC2844..
2N6604	Si-NPN	UHF,25V,50mA,>3,5GHz	52r	Mot	BFQ72,BFT65,2SC2844
2N6605	Thy-50Hz	30V,0,275A(Ta=55°),Igt/Ih<0,2/<5mA	2a$	Mot,Tag	TAG06Y,(TIC44,TIC60,MCR100-3,..)
2N6606	Thy-50Hz	=2N6605:60V	2a$	-	TAG06YY,(TIC46,TIC62,MCR100-3,..)
2N6607	Thy-50Hz	=2N6605:100V	2a$	-	TAG06A,(TIC46,TIC62,MCR100-3,..)
2N6608	Thy-50Hz	=2N6605:200V	2a$	-	TAG06B,(TIC47,TIC64,MCR100-4,..)
2N6609	Si-PNP	AF,Sw-Pow,160/140V,16A,150W,>2MHz	23a$	Mot,Rca	BD746F,MJ15016,2SA1117,2SA1147
2N661	Ge-PNP	AF,Sw,25/9/12V,1A,0,2W,20MHz	2a	USA	AC128,AC153,AC188,2SB405..
2N6617	Si-NPN	UHF,-/16V,10mA,0,15W,8GHz	51r	Hew	BFQ33,BFQ77,2SC1948
2N6618	Si-NPN	UHF,35V,20mA,0,3W(TG=125),8GHz	51r	Hew,Mot	BFQ33,BFQ77,2SC1948
2N6619	Si-NPN	=BFR35A	-	Sie	→BFR35A
2N662	Ge-PNP	AF,Sw,25/10/12V,1A,0,2W,8MHz	2a	USA	AC128,AC153,AC188,2SB405..
2N6620	Si-NPN	=BFR34A	-	Sie	→BFR34A
2N6621	Si-NPN	=BFW92	-	Sie	→BFW92
2N6622	Si-NPN	Sw,Pow,800V,10A,45W(Tc=100°),>4MHz	23a$	Amp	BU512(A),BUW26,BUW35..36,BUX81,..
2N663	Ge-PNP	AF,Sw-Pow,50V,Ueb=20V,4A,35W	23a$	USA	AD149,AUY19..20,2N1529..48
2N6648	Si-P-Darl+Di	AF,Sw-Pow,40V,10A,100W,B>1000	23a$	Mot,Rca	BDV64,BDX84,BDX86,BDX88C,MJ2500..
2N6649	Si-P-Darl+Di	=2N6648:60V	23a$	-	BDV64,BDX84A,BDX86A,BDX88C,MJ2500..
2N665	Ge-PNP	AF,Sw-Pow,80V,Ueb=40V,3A,35W	23a$	USA,Mot	AL102..103,AUY20,2N2141,2N2146..
2N6650	Si-P-Darl+Di	=2N6648:80V	23a$	-	BDV64A,BDX84B,BDX86B,MJ2501..
2N6653	Si-NPN	Sw,Pow,350/300V,20A,150W,>25MHz	23a$	Gsi,Stc	BUV24,BUX24,2SC3085
2N6654	Si-NPN	=2N6653:400/350V	23a$	-	BUV24,BUX24,2SC3085
2N6655	Si-NPN	=2N6653:450/400V	23a$	-	BUV24,BUX24,2SC3085
2N6656	MOS-N-FET-e	V-MOS,35V,2A,25W,<1,8e,<10/10nS	23a$	Sgs,Six	BUZ63,2SK259..260
2N6657	MOS-N-FET-e	V-MOS,60V,2A,25W,<3e,<10/10nS	23a$	Sgs,Six	BUZ62,2SK259..260
2N6658	MOS-N-FET-e	V-MOS,90V,2A,25W,<4Ω,<10/10nS	23a$	Sgs,Six	BUZ63,2SK259..260
2N6659	MOS-N-FET-e	Sw,Pow,35V,2A,6,2W(Tc=25°),<1,8Ω(5A)	2a$	Mot,Phi,Sgs	-
2N6660	MOS-N-FET-e	Sw,Pow,60V,2A,6,2W(Tc=25°),<3Ω(5A)	2a$	=2N6659	-
2N6661	MOS-N-FET-e	Sw,Pow,90V,2A,6,2W(Tc=25°),<4Ω(5A)	2a$	-	-
2N6665	Si-NPN	UHF,LN,20V,0,125A,0,45W,2GHz	5g	Miv	2SC2408,(BFR95)
2N6666	Si-P-Darl+Di	AF,Sw-Pow,40V,8A,65W,B>1000	17j$	Mot,Rca	BD644,BD896,BDW74,BDX54B..
2N6667	Si-P-Darl+Di	=2N6666:60V	17j$	Mot,Rca	BD646,BD898,BDW74A,BDX54A..
2N6668	Si-P-Darl+Di	=2N6666:80V	17j$	Mot,Rca	BD648,BD900,BDW74B,BDX54B..
2N6669	Si-NPN	AF,Sw-Pow,40V,10A,40W,>10MHz	17j$	Rca	BD705,BD743,BD805,BD905..
2N6670	Si-NPN	AM-Pow,80V,1,5A,Pq=5W(40MHz)	13g$	RCA	-
2N6671	Si-NPN	Sw,Pow,450/300V,5A,150W,>15MHz	23a$	Ferranti	BUW24..26,BUW34..36,BUW72..
2N6672	Si-NPN	=2N6671:550/350V	23a$	-	BUW25..26,BUW35..36,BUX80..
2N6673	Si-NPN	=2N6671:650/400V	23a$	-	BUW26,BUW35..36,BUX80..81..

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2N6674	Si-NPN	Sw,Pow,450/300V,10A,175W,>15MHz	23a$	Ferranti	BUV25,BUW44,BUW75,BUX25..
2N6675	Si-NPN	=2N6674:650/400V	23a$	-	BUS13(A),BUW44..46,BUX48(A..C)..
2N6676	Si-NPN	Sw,Pow,450/300V,15A,175W,>15MHz	23a$	USA,Mot,Tho	BUF420M,BUV25,BUW44..46,BUX25,BUX48..
2N6677	Si-NPN	=2N6676:550/350V	23a$	-	BUF420M,BUS13(A),BUW45..46,BUX48A..C)..
2N6678	Si-NPN	=2N6676:650/400V	23a$	-	BUF420M,BUS13(A),BUW45..46,BUX48A..C)..
2N6679	Si-NPN	UHF,30V,70mA,>4GHz	52r	Mot	BFQ82,BFQ196,2SC3603
2N6681	Thy-50Hz	100V,1A,Igt/Ih<0,2/<5mA	7e	Tho,Uni	TAG59A,BT149A,MCR606-3
2N6682	Thy-50Hz	=2N6681:200V	7e	-	TAG59B,BT149B,MCR606-4
2N6683	Thy-50Hz	=2N6681:400V	7e	-	TAG59D,BT149D,MCR606-6
2N6684	Thy-50Hz	=2N6681:600V	7e	-	TAG59M,BT149M,MCR606-8
2N6685	Thy-50Hz	=2N6681:800V	7e	-	(TAG615-800)
2N6686	Si-NPN	Sw,Pow,260/160V,25A,200W,>20MHz	23a$	Ferranti	BUV12,BUW73,BUX12
2N6687	Si-NPN	=2N6686:280/180V	23a$	-	BUV12,BUW73,BUX12
2N6688	Si-NPN	=2N6686:300/200V,20A	23a$	-	BUV12,BUW73,BUX12
2N6689	Si-NPN	Sw,Pow,450/300V,15A,175W,>15MHz	49a	Rca	-
2N669	Ge-PNP	AF,Sw-Pow,40V,3A,90W	23a$	USA,Mot	2N1529..1548,2N3611..18
2N6690	Si-NPN	=2N6689:650/400V	49a	-	-
2N6691	Si-NPN	Sw,Pow,450/300V,15A,175W,>15MHz	49a	Rca	-
2N6692	Si-NPN	=2N6691:550/350V	49a	-	-
2N6693	Si-NPN	=2N6691:650/400V	49a	-	-
2N67	Ge-PNP	Ueb=50V,0,05A,0,1W	-	Wes	-
2N670	Ge-PNP	AF,Sw,Chopper,40/40/40V,2A,0,3W	2a*	Spe,Ssi	-
2N6702	Si-NPN	Sw,Pow,140/90V,7A,50W,>50MHz	17j$	Rca,Sgs	BU409,BUV26,BUW64A..C,TIP150..152..
2N6703	Si-NPN	=2N6702:160/110V	17j$	-	BU409,BUW64C,TIP150..152..
2N6704	Si-NPN	=2N6702:180/130V	17j$	-	BU409,BUW64C,TIP150..152..
2N6705	Si-NPN	GenP,60V,1A,1,2W,>50MHz	30c$	Gen,Nsc	2SD1281..82,(BD517,BD525,..)
2N6706	Si-NPN	=2N6705:80V	30c$	-	2SD1281..82,(BD519,BD527,..)
2N6707	Si-NPN	=2N6705:100V	30c$	-	2SD1281..82,(BD529)
2N6708	Si-PNP	GenP,60V,1A,1,2W,>50MHz	30c$	Gen,Nsc	2SB957..958,(BD518,BD526,..)
2N6709	Si-PNP	=2N6708:80V	30c$	-	2SB957..958,(BD520,BD528,..)
2N671	Ge-PNP	=2N670:1W	2a*	Spe,Ssi	-
2N6710	Si-PNP	=2N6708:100V	30c$	-	2SB957..958,(BD530)
2N6711	Si-NPN	Vid,160V,0,1A,1,2W,50MHz	30c$	Gen,Nsc	(BF380..382,BF460..462,BF757..759)
2N6712	Si-NPN	=2N6711:250V	30c$	Gen,Nsc	(BF381..382,BF460..462,BF757..759)
2N6713	Si-NPN	=2N6711:300V	30c$	Gen,Nsc	(BF382,BF461..462,BF758..759)
2N6714	Si-NPN	GenP,40V,2A,1,2W,>50MHz	30e$	Gen,Nsc	2SD1078..79,(BD509,BD517,..)
2N6714[Ztx]	Si-NPN	GenP,40V,1A,1W,>50MHz	7e	Ztx	BC635,2SD667(A),2SD1225,2SD1616(A)..
2N6715	Si-NPN	=2N6714[Ztx]:50V	40e	Ztx	BC635,2SD1051,2SD1225,2SD1616(A)..
2N6716	Si-NPN	GenP,60V,2A,1,2W,>50MHz	30e$	Gen,Nsc	2SD1281..82,(BD517,BD525,..)
2N6717	Si-NPN	=2N6716:80V	30e$	Gen,Nsc	2SD1281..82,(BD519,BD527,..)
2N6718	Si-NPN	=2N6716:100V	40e	Ztx	BC639,2SD667(A),2SD1616A,2SD1768..
2N6719	Si-NPN	Sw,Vid,300V,0,1A,1,2W,>30MHz	30e$	Gen,Nsc	2SC2870,2SC2924,2SC3408,(BF617,..)
2N672	Ge-PNP	AF,Sw,Chopper,25/25/25V,2A,0,3W	2a*	Spe,Ssi	-
2N6720	Si-NPN	Sw,Vid,175V,1A,2W,>30MHz	30e$	Nsc	2SC2885,2SC2946,(BF466..468,..)
2N6721	Si-NPN	=2N6721:225V	30e$	Nsc	2SC2885,2SC2946,(BF467..468,..)
2N6722	Si-NPN	=2N6721:275V	30e$	Nsc	2SC2885,2SC2946,(BF468,BF668,..)
2N6723	Si-NPN	=2N6721:325V	30e$	Nsc	2SC2885,2SC2946,(BF468,BF668,..)
2N6724	Si-NPN-Darl	AF-Dr/Out,50V,2A,1W,B>15000	30e$	Gen,Nsc	2SD1222,2SD1759,(BD411..412)
2N6725	Si-NPN-Darl	=2N6724:60V	30e$	Gen,Nsc	2SD1222,2SD1759
2N6726	Si-PNP	AF-Dr/Out,40V,2A,1,2W,>50MHz	30e$	Gen,Nsc	2SB838..839,(BD518,BD526,..)
2N6727	Si-PNP	=2N6726:50V	30e$	Gen,Nsc	2SB838..839,(BD518,BD526,..)
2N6727	Si-PNP	=2N6726[Ztx]:50V	40e	Ztx	BC638,2SB647(A),2SB734,2SB1116(A),..
2N6728	Si-PNP	GenP,60V,1A,1W,>50MHz	40e	Ztx	BC638,2SB647(A),2SB734,2SB1116(A),..
2N6728	Si-PNP	GenP,60V,2A,1,2W,>50MHz	30e$	Gen,Nsc	2SB957..958,(BD518,BD526,..)
2N6729	Si-PNP	=2N6728:80V	30e$	Gen,Nsc	2SB957..958,(BD520,BD528,..)
2N6729	Si-PNP	=2N6728[Ztx]:80V	40e	Ztx	BC640,2SB647(A),2SB1041,2SB1116A..
2N673	Ge-PNP	=2N672:1W	2a*	Spe,Ssi	-
2N6730	Si-PNP	=2N6728:100V	30e$	Gen,Nsc	2SB957..958,(BD530)
2N6730	Si-PNP	=2N6728[Ztx]:100V	40e	Ztx	BC640,2SB647(A),2SB984,2SA1708..
2N6731	Si-NPN	GenP,100V,1A,2W,>50MHz	30e$	Nsc	2SD1281..84,(BD529)
2N6732	Si-PNP	GenP,100V,1A,2W,>50MHz	30e$	Nsc	2SB957..960,(BD530)
2N6733	Si-NPN	Vid,160V,0,1A,1,2W,>50MHz	30e$	Gen,Nsc	2SC2870,2SC2924,2SC3408,(BF617,..)
2N6734	Si-NPN	=2N6733:250V	30e$	-	2SC2870,2SC2924,2SC3408,(BF617,..)
2N6735	Si-NPN	=2N6733:300V	30e$	-	2SC2870,2SC2924,2SC3408,(BF617,..)

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2N6737	Si-NPN	Sw,80V,>300MHz,<-/60nS	30e$	Nsc	-
2N6738	Si-NPN	Sw,Pow,450/300V,8A,100W,>15MHz	17j$	Fer,Rca	BUT54,BUT56(A),2SC3039,2SC4106..
2N6739	Si-NPN	=2N6738:550/350V	17j$	-	BUT54,BUT56(A),2SC3039,2SC4106..
2N674	Ge-PNP	AF,Sw,Chopper,75/75/70V,2A,0,3W	2a*	Spe,Ssi	-
2N6740	Si-NPN	=2N6738:650/400V	17j$	-	BUT54,BUT56(A),MJE13006..07..
2N675	Ge-PNP	=2N674:1W	2a*	Spe,Ssi	-
2N6751	Si-NPN	Sw,Pow,800/400V,10A,150W,>15MHz	23a$	Fer,Rca	BUS12(A),BUW35..36,BUX80..81..
2N6752	Si-NPN	=2N6751:850/450V	23a$	-	BUS12(A),BUW36,BUX81,MJ8504..
2N6753	Si-NPN	=2N6751:900/500V	23a$	-	BUS12A,BUW36,BUX81,MJ8504..
2N6754	Si-NPN	=2N6751:1000/500V	23a$	-	BUS12A,BUX81,MJ8504,2SC3215..
2N6755	MOS-N-FET-e	=2N6756:60V,8A,<0,25Ω(5A)	23a$	-	2SK398..399,2SK500,2SK633
2N6756	MOS-N-FET-e	V-MOS,Sw,Pow,100V,14A,75W,<0,18Ω(5A)	23a$	USA,Inr,Mot	BUZ36,BUZ350,2SK622
2N6757	MOS-N-FET-e	=2N6758:150V,8A,<0,6Ω(5A)	23a$	-	2SK399,2SK401,2SK631,2SK633
2N6758	MOS-N-FET-e	V-MOS,Sw,Pow,200V,9A,75W,<0,4Ω(5A)	23a$	USA,Inr,Mot	2SK412,2SK633
2N6759	MOS-N-FET-e	V-MOS,Sw,Pow,350V,4,5A,75W,<1,5Ω(5A)	23a$	USA,Inr,Mot	BUZ63,2SK259..260
2N676	Ge/Si-P-Darl	80V,7A,B>1000,<350/-nS	-	Adv	-
2N6760	MOS-N-FET-e	V-MOS,Sw,Pow,400V,5,5A,75W,<1Ω(3,5A)	23a$	USA,Inr,Mot	BUZ63,2SK260,2SK298
2N6761	MOS-N-FET-e	=2N6762:450V,4A,<2Ω(2,5A)	23a$	-	BUZ84,2SK351
2N6762	MOS-N-FET-e	V-MOS,Sw,Pow,500V,4,5A,75W,<1,5Ω(5A)	23a$	USA,Inr,Mot	BUZ84,2SK351
2N6763	MOS-N-FET-e	=2N6764:60V,31A,<0,08Ω(20A)	23a$	-	BUZ24,BUZ349,2SK561,2SK906
2N6764	MOS-N-FET-e	V-MOS,Sw,Pow,100V,38A,150W,<0,055Ω	23a$	USA,Inr,Mot	BUZ345,2SK850
2N6765	MOS-N-FET-e	=2N6766:150V,16A,<0,12Ω(10A)	23a$	-	BUZ36,BUZ350,2SK622
2N6766	MOS-N-FET-e	V-MOS,Sw,Pow,200V,30A,T50W,<0,085Ω	23a$	USA,Inr,Mot	-
2N6767	MOS-N-FET-e	=2N6768:350V,12A,<0,4Ω(7,7(A)	23a$	-	BUZ64,BUZ325,2SK312
2N6768	MOS-N-FET-e	V-MOS,Sw,Pow,400V,14A,150W,<0,3Ω(5A)	23a$	USA,Inr,Mot	BUZ323,BUZ338,2SK788,2SK899
2N6769	MOS-N-FET-e	=2N6770:450V,11A,<0,5Ω(5A)	23a$	-	BUZ45,BUZ339,BUZ384,2SK512..
2N677	Ge-PNP	AF,Sw-Pow,50/20/25V,15A,90W,B>20	23a$	USA	AUY29,2N1550..2,2N1554..6,2N1559..0
2N6770	MOS-N-FET-e	V-MOS,Sw,Pow,500V,12A,150W,<0,4Ω(5A)	23a$	USA,Inr,Mot	BUZ45,BUZ339,BUZ384,2SK512..
2N6771	Si-NPN	Sw,Pow,450/300V,1A,40W,>10MHz	17j$	Fer,Rca	BUW40(A,B),BUX84..85,TIP49..50..
2N6772	Si-NPN	=2N6771:550/350V	17j$	-	BUW40A,B,BUX84..85,2SC3352..
2N6773	Si-NPN	=2N6771:650/400V	17j$	-	BUW40B,BUX84..85,2SC3352..
2N6774	Si-NPN+Diode	Sw,Pow,450/300V,15A,175W,>15MHz	23a$	RCA	-
2N6775	Si-NPN+Diode	=2N6774:550/350V	23a$	-	-
2N6776	Si-NPN+Diode	=2N6774:650/400V	23a$	-	-
2N677A	Ge-PNP	=2N677:60/30/25V	23a$	-	2N1550..52,2N1554..56,2N1559..60
2N677B	Ge-PNP	=2N677:90/60/25V	23a$	-	2N1552,2N1556,2N1560
2N677C	Ge-PNP	=2N677:100/70/25V	23a$	-	2N1552,2N1556,2N1560
2N678	Ge-PNP	AF,Sw-Pow,50/20/25V,15A,90W,B>50	23a$	USA	AUY29,2N1550..2,2N1554..6,2N1559..0
2N6782	MOS-N-FET-e	V-MOS,Sw,100V,3,5A,15W,<0,6Ω(5A)	2a$	Inr,Mot	(2SK429..430)
2N6784	MOS-N-FET-e	V-MOS,Sw,200V,2,25A,15W,<1,5Ω(1,5A)	2a$	Inr,Mot	BST95
2N6786	MOS-N-FET-e	V-MOS,Sw,400V,1,25A,15W,<3,6Ω(0,5A)	2a$	Inr	(2SK535,2SK579..580)
2N6788	MOS-N-FET-e	V-MOS,AFast-Sw,100V,6A,20W,<0,3Ω(3,5A)	2a$	Inr,Mot,Six	-
2N678A	Ge-PNP	=2N678:60/30/25V	23a$	-	2N1550..52,2N1554..56,2N1559..60
2N678B	Ge-PNP	=2N678:90/60/25V	23a$	-	2N1552,2N1556,2N1560
2N678C	Ge-PNP	=2N678:100/70/25V	23a$	-	2N1552,2N1556,2N1560
2N679	Ge-NPN	AF,Sw,25V,0,15W,3MHz	2a	USA	AC127,ASY28..29
2N6790	MOS-N-FET-e	V-MOS,Sw,200V,3,5A,20W,<0,8Ω(2,5A)	2a$	Inr,Six	-
2N6792	MOS-N-FET-e	V-MOS,Sw,400V,2A,20W,<1,8Ω(1,25A)	2a$	Inr,Six	-
2N6794	MOS-N-FET-e	V-MOS,Sw,500V,1,5A,20W,<3Ω(5A)	2a$	Inr,Six	-
2N6796	MOS-N-FET-e	V-MOS,Sw,100V,8A,25W,<0,18Ω(5A)	2a$	Inr,Six	-
2N6798	MOS-N-FET-e	V-MOS,Sw,200V,5,5A,25W,<0,4Ω(3,5A)	2a$	Inr,Six	-
2N68(/13)	Ge-PNP	AF-Pow,30V,Ueb=15V,1,5A,0,4MHz	?37	USA	-
2N680	Ge-PNP	AF,20V,0,15A,0,15W,3MHz	?1a	USA	AC125..126,AC151,2SB54,2SB56
2N6800	MOS-N-FET-e	V-MOS,400V,3A,25W,<1Ω(5A),<65/90nS	2a$	Inr,Six	-
2N6802	MOS-N-FET-e	V-MOS,Sw,500V,3,5A,25W,<1,5Ω(1,5A)	2a$	Inr,Six	-
2N6804	MOS-P-FET-e	V-MOS,100V,11A,75W,<0,3Ω(6,5A)	23a$	Inr	2SJ112..113
2N6806	MOS-P-FET-e	V-MOS,200V,6,5A,75W,<0,8Ω(5A)	23a$	Inr	2SJ56,2SJ114
2N681(A)	Thy-50Hz	25V,16A(Tc=65°),Igt/Ih<40/<50mA	21b$	USA,EUR	T12N100,MCR70-1,C228U,2N3896..
2N681(A)S	Thy-Fast	=2N681:<12µS	21b$	-	T12F100,C234U,MCR1718-5
2N682(A)	Thy-50Hz	=2N681:50V	21b$	-	T12N100,MCR70-2,C228F,2N3896..
2N682(A)S	Thy-Fast	=2N682:<12µS	21b$	-	T12F100,C234F,MCR1718-5
2N6823	MOS-N-FET-e	V-MOS,600V,3A,100W,<2,8Ω(5A)	23a$	Mot	BUZ307,BUZ360..361,2SK415,2SK954
2N6826	MOS-N-FET-e	V-MOS,600V,6A,150W,<1,6Ω(5A)	23a$	Mot	BUZ94,BUZ332A,2SK684,2SK1032
2N683(A)	Thy-50Hz	=2N681:100V	21b$	-	T12N100,MCR70-3,C228A,2N3896..

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2N683(A)S	Thy-Fast	=2N683: <12µS	21b$	-	T12F100, C234A, MCR1718-5
2N6833	Si-NPN	Sw, Pow, SMPS, 850/450V, 5A, 80W, >15MHz	17j$	Mot	BUT11(A), BUT46(A), BUV46(A), 2SC3047,..
2N6834	Si-NPN	=2N6833: 125W	23a$	-	BU426(A), BU526(A), BUS11(A), BUW11(A)..
2N6835	Si-NPN	Sw, Pow, SMPS, 850/450V, 8A, 150W, >10MHz	23a$	Motorola	BU426(A), BU526(A), BUS12(A), BUW12(A)..
2N6836	Si-NPN	Sw, Pow, SMPS, 850/450V, 15A, 175W, >10MHz	23a$	Motorola	BUS13(A), BUW46, BUX48(A..C)..
2N6837	Si-NPN	Sw, Pow, SMPS, 850/450V, 20A, 250W, >10MHz	23a$	Motorola	BUS14(A), BU598(A), BUX348(A)..
2N684(A)	Thy-50Hz	=2N681: 150V	21b$	-	T12N200, C228B, 2N3897, MCR3935-4..
2N684(A)S	Thy-Fast	=2N684: <12µS	21b$	-	T12F200, C234B, MCR1718-5
2N6845	MOS-P-FET-e	V-MOS, 100V, 4A, 20W, <0,6Ω(2,25A)	2a$	Mot	-
2N6847	MOS-P-FET-e	V-MOS, 200V, 2,5A, 20W, <1,5Ω(2,25A)	2a$	Mot	-
2N6849	MOS-P-FET-e	V-MOS, 100V, 6,5A, 25W, <0,3Ω(4,5A)	2a$	Mot, Six	-
2N685(A)	Thy-50Hz	=2N681: 200V	21b$	-	T12N200, C228B, 2N3897, MCR3935-4..
2N685(A)S	Thy-Fast	=2N685: <12µS	21b$	-	T12F200, C234B, MCR1718-5
2N6851	MOS-P-FET-e	V-MOS, 200V, 4A, 25W, <0,8Ω(2,5A)	2a$	Mot, Six	-
2N686(A)	Thy-50Hz	=2N681: 250V	21b$	-	T12N300, C228C, 2N3898, MCR3935-5..
2N686(A)S	Thy-Fast	=2N686: <12µS	21b$	-	T12F300, C234C, MCR1718-5
2N687(A)	Thy-50Hz	=2N681: 300V	21b$	-	T12N300, C228C, 2N3898, MCR3935-5..
2N687(A)S	Thy-Fast	=2N687: <12µS	21b$	-	T12F300, C234C, MCR1718-5
2N688(A)	Thy-50Hz	=2N681: 400V	21b$	-	T12N400, C228D, 2N3898, MCR3935-6..
2N688(A)S	Thy-Fast	=2N688: <12µS	21b$	-	T12F400, C234D, MCR1718-6
2N689(A)	Thy-50Hz	=2N681: 500V	21b$	-	T12N500, C228E, 2N3899, MCR3935-7..
2N689(A)S	Thy-Fast	=2N689: <12µS	21b$	-	T12F500, C234E, MCR1718-7
2N6895	MOS-P-FET-e	V-MOS, 100V, 1,16A, 8,33W, <3,65Ω	2a$	Inr	-
2N6896	MOS-P-FET-e	V-MOS, 100V, 6A, 60W, <0,6Ω(3,5A)	23a$	Inr	2SJ55..56, 2SJ115, 2SJ118..119
2N6897	MOS-P-FET-e	V-MOS, 100V, 12A, 100W, <0,3Ω(7,2A)	23a$	Inr	2SJ112..113, 2SJ127, 2SJ131
2N6898	MOS-P-FET-e	V-MOS, 100V, 25A, 150W, <0,2Ω(15,5A)	23a$	Inr	-
2N690(A)	Thy-50Hz	=2N681: 600V	21b$	-	T12N600, C228M, 2N3899, MCR3935-8..
2N690(A)S	Thy-Fast	=2N690: <12µS	21b$	-	T12F600, C234M, MCR1718-8
2N6901	MOS-N-FET-e	V-MOS, LogL, 100V, 1,69A, <1,4Ω(5A)	2a$	Inr	-
2N6902	MOS-N-FET-e	V-MOS, LogL, 100V, 12A, 75W, <0,2Ω	23a$	Inr	2N6765
2N6903	MOS-N-FET-e	V-MOS, LogL, 200V, 0,98A, 8,33W, <3,65Ω	2a$	Inr	-
2N6904	MOS-N-FET-e	V-MOS, Logl, 200V, 8A, 75W, <0,6Ω	23a$	Inr	-
2N6905	N-FET	Dual, 55V, Idss=0,5..10mA, Ugs<5mV	81	Six	-
2N6906	N-FET	=2N6905: ?UµS<10mV	81	-	-
2N6907	N-FET	=2N6905: ?UµS<25mV	81	-	-
2N6908	N-FET	30V, Up<-1,8V	5	Six	-
2N6909	N-FET	30V, Up<-2,3V	5	Six	-
2N691(A)	Thy-50Hz	=2N681: 700V	21b$	-	T12N700, MCR3935-9, BStE4146N..
2N691(A)S	Thy-Fast	=2N691: <12µS	21b$	-	T12F700, TAG35S-700
2N6910	N-FET	30V, Up<-3,5V	5	Six	-
2N692(A)	Thy-50Hz	=2N681: 800V	21b$	-	T12N800, MCR3935-10, BStE4153N..
2N692(A)S	Thy-Fast	=2N692: <12µS	21b$	-	T12F800, TAG35S-800
2N6928	Si-NPN	Sw, Pow, 450/300V, 8A, 100W, <500/2900nS	17j$	STE	MJE13006..07, BUT12(A), BUT56(A)..
2N6929	Si-NPN	=2N6928: 550/350V	17j$	-	MJE13006..07, BUT12(A), BUT56(A)..
2N6930	Si-NPN	=2N6928: 650/400V	17j$	-	MJE13006..07, BUT12(A), BUT56(A)..
2N6931	Si-NPN	Sw-Reg, 450/300V, 10A, 150W, <0,8/3µS	18j$	STE	BUV47(A), BUW12(A), BUW13(A), 2SC4157,..
2N6932	Si-NPN	=2N3932: 650/400V	18j$	-	BUV47(A), BUW12(A), BUW13(A), 2SC4157,..
2N6933	Si-NPN	Sw-Reg, 450/300V, 15A, 175W, <0,8/3µS	18j$	STE	BUP23(A..C), BUV48(A), BUW13(A)..
2N6934	Si-NPN	=2N6933: 550/350V	18j$	-	BUP23(A..C), BUV48(A), BUW13(A)..
2N6935	Si-NPN	=2N6933: 650/400V	18j$	-	BUP23(A..C), BUV48(A), BUW13(A)..
2N694	Ge-PNP	VHF, 30V, 0,05A, 0,1W, 500MHz	5g	Wes	AF139, AF239(S)
2N695	Ge-PNP	S/VHF, 15V, 0,05A, 0,075W, 250MHz	5g	Sty	AF106, AF109R, AF306
2N696(A,S)	Si-NPN	AF, Sw, 60V, 1A, 0,6(A:0,8)W, >40MHz	2a$	USA, EUR	BC140..141, BC300..302, 2N3053..
2N6962	MOS-N-FET-e	V-MOS, 100V, 30A, on=0,6Ω	49	Six	-
2N6963	MOS-N-FET-e	V-MOS, 200V, 30A, on=0,09Ω	49	Six	-
2N6964	MOS-N-FET-e	V-MOS, 400V, 15A, on=0,3Ω	49	Six	-
2N6965	MOS-N-FET-e	V-MOS, 500V, 13A, on=0,4e	49	Six	-
2N697	Si-NPN	60V, 1A, 0.6W, <50MHz	-	-	-
2N697(A,S)	Si-NPN	AF, Sw, 60V, 1A, 0,6(A:0,8)W, >50MHz	2a$	USA, EUR	BC140..141, BC300..302, 2N3053..
2N698	Si-NPN	AF, Sw, 120V, 1A, 0,8W, 70MHz	2a$	USA, Mot, Sgs	BSS42..43, BSW67..68, BSX47, 2N2405..
2N6985	Si-NPN	UHF, Push-Pull, 60V, 16A, Pq=125W(400MHz)	-	Mot	-
2N6986	Si-NPN	UHF, Push-Pull, 60V, 16A, Pq=100W(500MHz)	-	Mot	-
2N699(A,B)	Si-NPN	AF, Sw, 120V, 1A, 0,6..0,8W, 100MHz	2a$	USA, Mot, Sgs	BSS42..43, BSW67..68, BSX47, 2N2405..
2N700(A,/18)	Ge-PNP	AM/FM, 25V, 0,05A, 0,075W, 800MHz	5g	USA, Mot	AF106, AF109R, AF139, AF239(S)

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2N7000	MOS-N-FET-e	V-MOS, 60V, 0,2A, 0,4W, <5e, <10/10ns	7e	Mot,Nsc,Phi	BS170, BST70, BST72, 2SK1337
2N7000P	MOS-N-FET-e	=2N7000:	40e	Ztx	BS170, BST70, BST72, 2SK1337
2N7001	MOS-N-FET-e	V-MOS, 240V, 50mA, <45Ω, <30/-nS	35	Mot	-
2N7002	MOS-N-FET-e*	V-MOS, 60V, 0,2W, 0,115A, <7,5Ω(0,5A)	35a	Six	→2N7002
2N7002	MOS-N-FET-e*	V-MOS, 60V, 115mA, 0,2W, <7,5Ω(0,5A), 60nS	35a	Phi	→2N7002
2N7004	MOS-N-FET	V-MOS, 100V, 1A, on=0,6Ω	4-DIP	Six	-
2N7005	MOS-N-FET	V-MOS, 200V, 0,6A, on=1,5Ω	4-DIP	Six	-
2N7006	MOS-N-FET	V-MOS, 350V, 0,32A, on=5e	4-DIP	Six	-
2N7007	MOS-N-FET-e	V-MOS, 240V, 65mA, 0,4W, <45Ω(20mA)	7e	Six,Stx	BN5254, BSS88..89, 2SK2169
2N7008	MOS-N-FET-e	V-MOS, 60V, 0,23A, 0,4W, <7,5Ω(50(A)	7e	Six,Stx	BS170, BST72, 2SK1336, 2SK1337
2N701	Ge-PNP	VHF, 30V, 0,075W, 200MHz	5g	Mot	AF106, AF109R, AF306
2N7010	MOS-N-FET	V-MOS, 60V, 1,3A, on=0,35e	30	Six	-
2N7012	MOS-N-FET	V-MOS, 60V, 1,2A, 1W, <0,35Ω, <50/55nS	4-DIP	Six	-
2N7013	MOS-N-FET	V-MOS, 40V, 1,2A, on=0,3e	4-DIP	Six	-
2N7016	MOS-N-FET	V-MOS, 60V, 0,6A, on=1e	4-DIP	Six	-
2N702	Si-NPN	GenP, 25V, 0,05A, 0,3W, 150MHz, B>20	2a$	USA,Mot	BC168, BC183, BC238, BC548, 2SD767..
2N703	Si-NPN	=2N702: B>40	2a$	USA,Mot	BC168, BC183, BC238, BC548, 2SD767..
2N705(A)	Ge-PNP	Sw, 15V, 0,05(A:0,1)A, 0,15W, 55/135nS	2a$	USA,Mot	ASZ21, 2N964A, 2N2635, 2N2955..57
2N7051	Si-NPN-Darl	100V, B>20k, >100MHz	7e	Nsc	-
2N7052	Si-NPN-Darl	100V, 1,5A, 0,625W, B=1..20k, >200MHz	7e	Nsc	2SD1660, 2SD1978, 2SD1981, 2SD2067,..
2N7053	Si-NPN-Darl	100V, 1,5A, 0,625W, B=1..20k, >200MHz	7e	Nsc	2SD1660, 2SD1978, 2SD1981, 2SD2067,..
2N7056	MOS-FET	V-MOS, 200V, 19A, 70W, on<0,1Ω(10A)	18	Sgs	-
2N7059	MOS-FET	V-MOS, 500V, 8A, 70W, on<0,45Ω(5A)	18	Sgs	-
2N706(A..C)	Si-NPN	Sw, 25V, 0,2A, 0,3W, 400MHz, <40/75nS, A:25V, B:25V, C:40V, 0,36W	2a$	USA,EUR	BSS11..12, BSX19..20, 2N2368..69(A),+
2N707	Si-NPN	VHF-Osc, 56V, 0,1A, 0,3W, 350MHz	2a$	USA,Mot,Sgs	BFX94..95
2N7071	MOS-N-FET-e	V-MOS, 100V, 23A, 100W, <0,1Ω(10A)	18f	Six	BUK426-100, (2SK622, 2SK629)
2N7072	MOS-N-FET-e	V-MOS, 200V, 16A, 100W, <0,2Ω(10A)	18f	Six	(BUZ350)
2N7073	MOS-N-FET-e	V-MOS, 400V, 9A, 100W, <0,55Ω(5,5A)	18f	Six	2SK1225, 2SK1328, (BUZ330..331, BUZ501)
2N7074	MOS-N-FET-e	V-MOS, 500V, 7A, 100W, <0,85Ω(4,5A)	18f	Six	2SK1206, (BUZ330..331, BUZ332A)
2N7075	MOS-N-FET-e	V-MOS, 100V, 30A, 150W, <65mΩ(20A)	18f	Six	(BUZ349, 2SK906)
2N7076	MOS-N-FET-e	V-MOS, 200V, 28A, 150W, <0,1Ω(10A)	18f	Six	(BUZ341, 2SK851)
2N7077	MOS-N-FET-e	V-MOS, 400V, 15A, 150W, <0,3Ω(9,8A)	18f	Six	2SK1268..1269, (BUZ323, 2SK788, 2SK899)
2N7078	MOS-N-FET-e	V-MOS, 500V, 13A, 150W, <0,4Ω(5A)	18f	Six	2SK1269, (BUZ338, 2SK725, 2SK788, 2SK899)
2N7079	MOS-P-FET-e	V-MOS, 100V, 17A, 100W, <0,21Ω(5A)	18f	Six	2SJ222
2N707A	Si-NPN	=2N707: 70V	2a$	-	-
2N708	Si-NPN	Sw, 40V, 0,2A, 0,36W, 480MHz, <40/70nS	2a$	USA,EUR	BSS10..11, BSX19..20, 2N2368..69(A),..
2N7080	MOS-P-FET-e	V-MOS, 200V, 9,5A, 100W, <0,5Ω(6,5A)	18f	Six	(2SJ114)
2N7081	MOS-N-FET-e	V-MOS, 100V, 12A, 45W, <0,15Ω(7,2A)	17c	Six	BUK545-100, 2SK1230, 2SK1305
2N7082	MOS-N-FET-e	V-MOS, 200V, 9A, 50W, <0,3Ω(5,5A)	17c	Six	BUK545-200, (BUZ30, BUZ73)
2N7085	MOS-N-FET-e	V-MOS, 100V, 20A, 60W, <75mΩ(10A)	17c	Six	2SK1307, 2SK1318, (BUZ21..22)
2N7086	MOS-N-FET-e	V-MOS, 100V, 14A, 60W, <0,16Ω(8,6A)	17c	Six	(BUZ30A)
2N7089	MOS-N-FET-e	V-MOS, 100V, 10A, 60W, <0,3Ω(6,5A)	17c	Six	BUK545-100, 2SK1230, 2SK1305, (BUZ72)
2N708A	Si-NPN	=2N708: 50V	2a$	-	BSS10..11, BSX19..20, 2N2368..69(A),..
2N709(A)	Si-NPN	Fast-Sw, 15V, 0,3(A:0,36)W, <15/15nS	2a$	USA,EUR	BSS11..12, BSY17..18, 2N2368..69(A),..
2N7090	MOS-N-FET-e	V-MOS, 200V, 5,7A, 60W, <0,8Ω(3,5A)	17c	Six	BUK444-200, BUZ73(A)F, (2SK924)
2N7091	MOS-N-FET-e	V-MOS, 100V, 14A, 70W, <0,2Ω(8,6A)	17c	Six	BUK445-100, 2SK1306, (2SK919, 2SK922)
2N7092	MOS-N-FET-e	V-MOS, 200V, 8A, 70W, <0,5Ω(5,5A)	17c	Six	BUK545-200, (BUZ30, BUZ73)
2N71	Ge-PNP	AF, Sw, 75V, 0,25A, 1W, 0,25MHz	-	Whs	-
2N710	Ge-PNP	Sw, 15V, 0,05A, 0,15W, <75/200nS	2a$	USA	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N7104	MOS-N-FET-e	30V, on<70Ω, <2/-nS	5	Six	-
2N7105	MOS-N-FET-e	30V, on<70Ω, <2/-nS	5	Six	-
2N7106	MOS-N-FET-e	10V, on<70e, <2/-nS	5	Six	-
2N7107	MOS-N-FET-e	10V, on<70e, <2/-nS	5	Six	-
2N7108	MOS-N-FET-e	20V, on<70e, <2/-nS	5	Six	-
2N7109	MOS-N-FET-e	20V, on<70e, <2/-nS	5	Six	-
2N710A	Ge-PNP	Sw, 15V, 0,05A, 0,15W, <75/125nS	2a$	USA	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N711(A,B)	Ge-PNP	Sw, 12V, 0,05..0,1A, 0,15W, <100/250nS, A:<100/300nS, B:<100/250nS	2a$	USA,Mot,Tix	ASZ21, 2N705(A), 2N2635, 2N2955..57
2N7116	MOS-N-FET-e	20V, on<70e, <2/-nS	16-DIP	Six	-
2N7117	MOS-N-FET-e	10V, on<70e, <2/-nS	16-DIP	Six	-
2N7118	MOS-N-FET-e	15V, on<70e, <2/-nS	16-DIP	Six	-
2N715	Si-NPN	HF-Dr, 50V, 0,1A, 0,5W, >70MHz	2a$	USA	BFX94..95
2N716	Si-NPN	=2N715: 70V	2a$	USA	-
2N717	Si-NPN	GenP, 60V, 0,5A, 0,4W, 300MHz, B>20	2a$	USA,EUR	BC337A, BC637, BC639, BCX24..
2N717A	Si-NPN	=2N717: 75V, 200MHz	2a$	-	BC639, BCX24, 2SD667, 2SD1226..

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2N718	Si-NPN	=2N717: B>40	2a$	USA,EUR	BC337A,BC637,BC639,BCX24..
2N718A	Si-NPN	=2N717: 75V,B>40	2a$	-	BC639,BCX24,2SD667,2SD1226..
2N719(A)	Si-NPN	GenP,120V,1A,0,4W,>40MHz,B>20	2a$	USA,Sgs,Tix	BCX22,2N3700..01,2SD667,2SD774..
2N72	Ge-PNP	HF,40V,Ueb=50V,8mA,0,05W,20MHz	-	Rca	AF124..127,AF200
2N720(A)	Si-NPN	=2N719: >50MHz,B>40	2a$	USA,Sgs,Tix	BCX22,2N3700..01,2SD667,2SD774..
2N721(A)	Si-NPN	GenP,50V,0,5A,0,4W,>50MHz,B>20	2a$	USA,EUR	BC337,BC637,BC639,BCX24..
2N722(A)	Si-NPN	=2N721: >60MHz,B>30	2a$	USA,EUR	BC337,BC637,BC639,BCX24..
2N7224	MOS-N-FET-e	V-MOS,100V,34A,150W,<0,081Ω(20A)	18f	Six	(2SK1149,2SK1435..1436)
2N7225	MOS-N-FET-e	V-MOS,200V,27,4A,150W,<0,105Ω(20A)	18f	Six	(2SK1670)
2N7227	MOS-N-FET-e	V-MOS,400V,14A,150W,<0,415Ω(10A)	18f	Six	(2SK1268..1269,2SK1453)
2N7228	MOS-N-FET-e	V-MOS,500V,12A,150W,<0,515Ω(10A)	18f	Six	(2SK1269,2SK1331,2SK1524)
2N725	Ge-PNP	Sw,15V,0,05A,0,15W,<70/100nS	2a$	Sty	ASZ21,2N705(A),2N2635,2N2955..57
2N726	Si-PNP	GenP,25V,0,05A,0,3W,>140MHz,B>15	2a$	USA,Mot,Tix	BC213,BC258,BC308,BC558,2SB725..
2N727	Si-PNP	=2N726: B>30	2a$	USA,Mot,Tix	BC213,BC258,BC308,BC558,2SB725..
2N728	Si-NPN	Fast-Sw,15V,0,1A,0,3W,>100MHz,18/-nS	2a$	Sem,Sty	BSS11..12,BSY17..18,2N2368..69(A),..
2N729	Si-NPN	=2N728: 30V	2a$	Sem,Sty	BSS11..12,BSX19..20,2N2368..69(A),..
2N73	Ge-PNP	Sw,-/50V,0,2W	-	Whs	(ASY48,ASY77)
2N730	Si-NPN	GenP,60V,1A,0,5W,>25MHz,B>20	2a$	USA,Mot,Tix	BC337A,BC637,BC639,BCX24..
2N731	Si-NPN	=2N730: B>40	2a$	USA,Mot,Tix	BC337A,BC637,BC639,BCX24..
2N734(A)	Si-NPN	AF,Sw,80V,0,05A,0,5W,150MHz,B>20	2a$	USA,Mot,Tix	BCS46,2SC1890(A),2SC2240,2SC2459..
2N735(A)	Si-NPN	=2N734: 180MHz,a>40	2a$	USA,Mot,Tix	BCS46,2SC1890(A),2SC2240,2SC2459..
2N736(A,B)	Si-NPN	=2N734: 180MHz,a>80,A,B:0,1A	2a$	USA,Mot,Tix	BCS46,2SC1890(A),2SC2240,2SC2459..
2N738(A)	Si-NPN	AF,Sw,125V,0,05A,0,5W,150MHz,B>20	2a$	USA,Mot,Tix	2SC1890A,2SC2240,2SC2459,2SC3245..
2N739(A)	Si-NPN	=2N738: 180MHz,a>30	2a$	USA,Mot,Tix	2SC1890A,2SC2240,2SC2459,2SC3245..
2N74	Ge-PNP	Sw,-/50V,0,2W	-	Whs	(ASY48,ASY77)
2N740(A)	Si-NPN	=2N738: 180MHz,a>80	2a$	USA,Mot,Tix	2SC1890A,2SC2240,2SC2459,2SC3245..
2N741(A)	Ge-PNP	VHF-Osc,15(A:20)V,0,1A,360MHz	2a$	USA,Mot	(AF139,AF239(S),AFY18)
2N742(A)	Si-NPN	AF,Sw,60V,0,1A,0,5W,>60MHz	2a$	USA	BC174,BC182,BC190,BCS46,2SD767..
2N743	Si-NPN	Fast-Sw,20V,0,2A,0,3W,<16/24nS	2a$	USA,EUR	BSS11..12,BSY17..18,2N2368..69(A),..
2N743A	Si-NPN	=2N743: 40V,<12/30nS	2a$	-	BSS11..12,BSX19..20,2N2368..69(A),..
2N744	Si-NPN	Fast-Sw,20V,0,2A,0,3W,<16/24nS	2a$	USA,EUR	BSS11..12,BSY17..18,2N2368..69(A),..
2N744A	Si-NPN	=2N744: 40V,<12/30nS	2a$	-	BSS11..12,BSY19..20,2N2368..69(A),..
2N745	Si-NPN	GenP,45V,0,02A,0,15W,30MHz	37b	Ray	BC167,BC182,BC237,BCS47,2SD767..
2N746	Si-NPN	GenP,45V,0,02A,0,15W,45MHz	37b	Ray	BC167,BC182,BC237,BCS47,2SD767..
2N747	Si-NPN	GenP,25V,0,05A,0,2W,60MHz	37b	Ray	BC168,BC183,BC238,BCS48,2SD767..
2N748	Si-NPN	GenP,30V,0,05A,0,2W,50MHz	37b	Ray	BC168,BC183,BC238,BCS48,2SD767..
2N749	Si-NPN	GenP,45V,0,05A,0,2W,75MHz	37b	Ray	BC167,BC182,BC237,BCS47,2SD767..
2N75	Ge-PNP	Sw,-/20V,0,2W	-	Whs	(ASY26,ASY48,ASY76..77)
2N750	Si-NPN	GenP,50V,0,05A,0,2W,40MHz	37b	Ray	BC167,BC182,BC237,BCS47,2SD767..
2N751	Si-NPN	GenP,20V,0,05A,0,2W,30MHz	37b	Ray	BC168,BC182,BC238,BCS48,2SD767..
2N752	Si-NPN	GenP,85V,0,1A,0,5W,>200MHz	2a$	USA	BCS46,2SC2240,2SC2459,2SC3245..
2N753	Si-NPN	Sw,25V,0,05A,0,3W,30/60nS	2a$	USA,EUR	BSS11..12,BSY17..18,2N2368..69(A),..
2N754	Si-NPN	GenP,60V,0,05A,0,3A,>30MHz	2a$	USA	BC174,BC182,BC190,BCS46,2SD767..
2N755	Si-NPN	=2N754: 100V	2a$	USA	2SC1890(A),2SC2240,2SC2459,2SC3245,..
2N756	Si-NPN	GenP,45V,0,1A,0,5W,>50MHz,B>12	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N756A	Si-NPN	=2N756: 60V	2a$	-	BC174,BC182,BC190,BCS46,2SD767..
2N757	Si-NPN	GenP,45V,0,1A,0,5W,>50MHz,B>18	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N757A	Si-NPN	=2N757: 60V	2a$	-	BC174,BC182,BC190,BCS46,2SD767..
2N758	Si-NPN	GenP,45V,0,1A,0,5W,>50MHz,B>18	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N758A,B	Si-NPN	=2N758: 60V	2a$	-	BC174,BC182,BC190,BCS46,2SD767..
2N759	Si-NPN	GenP,45V,0,1A,0,5W,>50MHz,B>36	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N759A,B	Si-NPN	=2N759: 60V	2a$	-	BC174,BC182,BC190,BCS46,2SD767..
2N76	Ge-PNP	AF,Sw,20V,0,01A,0,05W,1MHz	1a$	Gen	AC125..126,AC151,ASY26..27
2N760	Si-NPN	GenP,45V,0,1A,0,5W,>50MHz,B>76	2a$	USA,Tix	BC167,BC182,BC237,BCS47,2SD767..
2N760A,B	Si-NPN	=2N760: 60V	2a$	-	BC174,BC182,BC190,BCS46,2SD767..
2N761	Si-NPN	GenP,50V,0,1A,0,5W,>50MHz,B>19	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N762	Si-NPN	=2N761: a>39	2a$	USA	BC167,BC182,BC237,BCS47,2SD767..
2N764	Thy-GTO	30V,0,2A,Igt/Ih<1/<5mA	2a	Sem,Sld	-
2N765	Thy-GTO	=2N764: 60V	2a	Sem,Sld	-
2N766	Thy-GTO	=2N764: 100V	2a	Sem,Sld	-
2N767	Thy-GTO	=2N764: 200V	2a	Sem,Sld	-
2N768	Ge-PNP	Sw,12V,0,1A,0,035W,>125MHz	2a	USA	ASZ21,2N960..967,2N2635,2N2955..57
2N769	Ge-PNP	Sw,12V,0,1A,0,035W,>100MHz	2a	USA	ASZ21,2N960..967,2N2635,2N2955..57
2N77	Ge-PNP	HF/Sw,25V,0,015A,0,035W,0,7MHz	37a	Csr,Etc	(AC125..126,AC151,ASY26..27)

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2N770	Si-NPN	HF,20V,0,1A,0,15W,125MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N771	Si-NPN	HF,20V,0,1A,0,15W,200MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N772	Si-NPN	HF,25V,0,1A,0,15W,110MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N773	Si-NPN	HF,20V,0,1A,0,15W,70MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N774	Si-NPN	HF,20V,0,1A,0,15W,90MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N775	Si-NPN	HF,20V,0,1A,0,15W,160MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N776	Si-NPN	HF,20V,0,1A,0,15W,120MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N777	Si-NPN	HF,20V,0,1A,0,15W,160MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N778	Si-NPN	HF,20V,0,1A,0,15W,180MHz	2a	Phc	BC238,BC548,BSW41,2N706A..
2N779(A,B)	Ge-PNP	Sw,15V,0,1A,0,06(B:0,15)W,>320MHz	2a	USA	ASZ21,2N964A,2N2635,2N2955..57
2N78	Ge-NPN	HF,15V,0,02A,0,065W,9MHz	?1a	Csr,Etc	(ASY28..29)
2N780	Si-NPN	GenP,45V,0,05A,0,3W,>60MHz	2a$	USA,Tix	BC167,BC182,BC237,BC547,2SD767..
2N781	Ge-PNP	Sw,15V,0,2A,0,15W,<60/70nS	2a	USA	2N705,2N960..967
2N782	Ge-PNP	Sw,12V,0,2A,0,15W,<75/75nS	2a	USA	2N705,2N960..967
2N783	Si-NPN	Fast-Sw,40V,0,2A,0,3W,>200MHz,<18/30nS	2a$	USA,Fch,Itt	BSS10..11,BSX19..20,2N2368..69(A),..
2N784	Si-NPN	Fast-Sw,30V,0,2A,0,3W,>200MHz,<20/40nS	2a$	USA,Fch,Itt	BSS10..11,BSX19..20,2N2368..69(A),..
2N784A	Si-NPN	=2N784: 40V	2a$	-	BSS10..11,BSX19..20,2N2368..69(A),..
2N785	Ge-PNP	12V,0,05W	-		-
2N789	Si-NPN	GenP,45V,0,025A,0,15W,>1MHz	37b	Ray	BC167,BC182,BC237,BC547,2SC1890+
2N78A	Ge-NPN	=2N78: 20V	?1a	-	(ASY28..29)
2N79	Ge-PNP	AF,Sw,30V,0,05A,0,035W,0,78MHz	1a	Rca	AC125..126,AC151,ASY26
2N790	Si-NPN	GenP,45V,0,025A,0,15W,>2MHz	37b	Ray	BC167,BC182,BC237,BC547,2SC1890+
2N791	Si-NPN	GenP,45V,0,025A,0,15W,>8MHz	37b	Ray	BC167,BC182,BC237,BC547,2SC1890+
2N792	Si-NPN	GenP,45V,0,025A,0,15W,>2MHz	37b	Ray	BC167,BC182,BC237,BC547,2SC1890+
2N793	Si-NPN	GenP,45V,0,025A,0,15W,>2MHz	37b	Ray	BC167,BC182,BC237,BC547,2SC1890+
2N794	Ge-PNP	Sw,13V,0,1A,0,12W,>25MHz,300/-nS	2a$	USA	ASZ21,2N705,2N960..967
2N795	Ge-PNP	Sw,13V,0,1A,0,12W,>35MHz,150/-nS	2a$	USA	ASZ21,2N705,2N960..967
2N796	Ge-PNP	Sw,12V,0,1A,0,12W,>50MHz,130/-nS	2a$	USA	ASZ21,2N705,2N960..967
2N797	Ge-NPN	VHF/Sw,20V,0,15A,0,15W,1000MHz	2a$	USA,Tix	-
2N799	Ge-PNP	AF,Sw,25V,0,1A,0,075W,>4MHz	37b	Ray	ASY26..27,ASY76..77
2N80	Ge-PNP	AF,Sw,25V,8mA,0,05W	?2a&	Cbs	AC125..126,AC151,ASY26..27
2N800	Ge-PNP	=2N799:	37b&	Ray	-
2N801	Ge-PNP	AF,Sw,30V,0,4A,0,075W,>3MHz	37b	Ray	ASY76..77
2N802	Ge-PNP	=2N801:	37b&	Ray	-
2N803	Ge-PNP	AF,Sw,30V,0,4A,0,075W,>5MHz	37b	Ray	ASY76..77
2N804	Ge-PNP	=2N803:	37b&	Ray	-
2N805	Ge-PNP	AF,Sw,30V,0,4A,0,075W,>10MHz	37b	Ray	ASY76..77
2N806	Ge-PNP	=2N805:	37b&	Ray	-
2N807	Ge-PNP	AF,Sw,25V,0,1A,0,075W,18MHz	37b	Ray	ASY26..27,ASY76..77
2N808	Ge-PNP	=2N807:	37b&	Ray	-
2N809	Ge-PNP	AF,Sw,30V,0,2A,0,075W,>3MHz	37b	Ray	ASY26..27,ASY76..77
2N81	Ge-PNP	AF,Sw,20V,15mA,0,05W	1a&	Gen	AC125..126,AC151,ASY26..27
2N810	Ge-PNP	=2N809:	37b&	Ray	-
2N811	Ge-PNP	AF,Sw,30V,0,2A,0,075W,>5MHz	37b	Ray	ASY26..27,ASY76..77
2N812	Ge-PNP	=2N811:	37b&	Ray	-
2N813	Ge-PNP	AF,Sw,30V,0,2A,0,075W,>15MHz	37b	Ray	ASY26..27,ASY76..77
2N814	Ge-PNP	=2N813:	37b&	Ray	-
2N815	Ge-NPN	AF,Sw,25V,0,2A,0,075W,8MHz	37b	Ray	ASY28..29,ASY73..75
2N816	Ge-NPN	=2N815:	37b&	Ray	-
2N817	Ge-NPN	AF,Sw,30V,0,4A,0,075W,>2,5MHz	37b	Ray	ASY73..75
2N818	Ge-NPN	=2N817:	37b&	Ray	-
2N819	Ge-NPN	AF,Sw,30V,0,4A,0,075W,>5MHz	37b	Ray	ASY73..75
2N82	Ge-PNP	AF,Sw,20V,15mA,0,035W	?2a&	Cbs	AC125..126,AC151,ASY26..27
2N820	Ge-NPN	=2N819:	37b&	Ray	-
2N821	Ge-NPN	AF,Sw,30V,0,4A,0,075W,>10MHz	37b	Ray	ASY73..75
2N822	Ge-NPN	=2N821:	37b&	Ray	-
2N823	Ge-NPN	AF,Sw,25V,0,1A,0,075W,>4MHz	37b	Ray	ASY28..29,ASY73..75
2N824	Ge-NPN	=2N823:	37b&	Ray	-
2N825	Ge-PNP	AF,Sw,30V,0,4A,0,07W,8MHz	37b	Ray,Sty	ASY76..77
2N826	Ge-PNP	=2N825:	37b&	Ray,Sty	-
2N827	Ge-PNP	Sw,20V,0,1A,0,15W,350MHz,25/30nS	2a$	USA,Mot	2N960..967
2N828(A)	Ge-PNP	Sw,15V,0,1A,0,15W,<70(A:<50)/100nS	2a$	USA,Mot	2N960..967
2N829	Ge-PNP	Sw,15V,0,1A,0,15W,400MHz,35/60nS	2a$	USA,Mot	2N960..967
2N83(A)	Ge-PNP	Sw,Dr-Pow,66V,Ueb=12V,2(A:3)A,10W	?37	Tra	-

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2N834	Si-NPN	Sw,40V,0,2A,0,3W,>350MHz,<33/75nS	2a$	USA,EUR	BSS10..11,BSX19..20,2N2368..69(A),..
2N834A	Si-NPN	=2N834:>500MHz,<16/24nS	2a$	-	BSS10..11,BSX19..20,2N2368..69(A),..
2N835	Si-NPN	Sw,25V,0,2A,0,3W,>300MHz,<20/35nS	2a$	USA,EUR	BSS10..11,BSX19..20,2N2368..69(A),..
2N837	Ge-PNP	Sw,12V,0,1A,0,15W,<30/90nS	2a$	USA	ASZ21,2N705,2N960..967
2N838	Ge-PNP	Fast-Sw,30V,0,1A,0,15W,450MHz,17/20nS	2a$	USA,Mot	2N960..967
2N839	Si-NPN	GenP,45V,0,05A,0,3W,>30MHz,B>15	2a$	USA	BC167,BC182,BC237,BC547,2SC1890+
2N84(A)	Ge-PNP	Sw,Dr-Pow,50V,Ueb=12V,2(A:3)A,10W	?37	Tra	-
2N840	Si-NPN	=2N839:B>30	2a$	USA,Mot	BC167,BC182,BC237,BC547,2SC1890+
2N841	Si-NPN	=2N839:>40MHz,B>60	2a$	USA,Mot	BC167,BC182,BC237,BC547,2SC1890+
2N842	Si-NPN	AF,Sw,45V,0,05A,0,3W,>30MHz,B>20	2a$	USA	BC167,BC182,BC237,BC547,2SC1890+
2N843	Si-NPN	=2N842:>40MHz,B>45	2a$	USA,Mot	BC167,BC182,BC237,BC547,2SC1890+
2N844	Si-NPN	AF,Sw,60V,0,05A,0,3W,>50MHz	2a$	USA	BC174,BC182,BC190,BC546,2SD767..
2N845	Si-NPN	=2N844:100V	2a$	USA	2SC1890A,2SC2240,2SC2459,2SD755..
2N846	Ge-PNP	Sw,15V,0,05A,0,06W,>320MHz	2a	Phc,Spr	ASZ21,2N705,2N960..967
2N846A,B	Ge-PNP	=2N846:0,1A,0,15W	2a	-	ASZ21,2N705,2N960..967
2N847	Si-NPN	Sw,40V,0,05A,0,2W,<32/58nS	2a	Ray	BSS10..11,BSV91..92,2N2368..69(A),..
2N848	Si-NPN	=2N847:20V	2a$	Ray	BSS10..11,BSV91..92,2N2368..69(A),..
2N849	Si-NPN	Sw,25V,0,05A,0,3W,>600MHz,<40/25nS	24c	Sca,Tix	BSS11..12,BSV91..92,2N2368..69(A),..
2N85	Ge-PNP	AF-Driver,30V,0,1A,0,2W,0,8MHz	?1e*	Tra	(AC125..126,AC151,2SB56)
2N850	Si-NPN	Sw,25V,0,05A,0,3W,>600MHz,<40/35nS	24c	Sca,Tix	BSS11..12,BSV91..92,2N2368..69(A),..
2N851	Si-NPN	Sw,20V,0,2A,0,3W,>900MHz,<16/24nS	24c	Sca,Tix	BSS11..12,BSX19..20,2N2368..69(A),..
2N852	Si-NPN	Sw,20V,0,2A,0,3W,>900MHz,<16/24nS	24c	Sca,Tix	BSS11..12,BSX19..20,2N2368..69(A),..
2N858	Si-PNP	AF,Sw,40/40/25V,0,05A,0,15W,>5MHz	2a	USA	2SA1246,2SA1253,(BC307,BC557,..)
2N859	Si-PNP	AF,Sw,40/40/25V,0,05A,0,15W,>6MHz	2a	USA	2SA1246,2SA1253,(BC307,BC557,..)
2N86	Ge-PNP	AF-Driver,45V,0,1A,0,2W,0,8MHz	?1e*	Tra	(2SB56A)
2N860	Si-PNP	AF,Sw,25/25/20V,0,05A,0,15W,>6,5MHz	2a	USA,Mot	2SA1246,2SA1253,(BC308,BC558,..)
2N861	Si-PNP	AF,Sw,25/25/20V,0,05A,0,15W,>7,5MHz	2a	USA	2SA1246,2SA1253,(BC308,BC558,..)
2N862	Si-PNP	AF,Sw,15/15/10V,0,05A,0,15W,>8MHz	2a	USA	2SA1246,2SA1253,(BC308,BC558,..)
2N863	Si-PNP	AF,Sw,15/15/10V,0,05A,0,15W,>10MHz	2a	USA	2SA1246,2SA1253,(BC308,BC558,..)
2N864	Si-PNP	AF,Sw,6/6/6V,0,05A,0,15W,>16MHz	2a	USA	2SA1246,2SA1253,(BC308,BC558,..)
2N864A	Si-PNP	=2N864:0,1A	2a	Tdy	2SA1246,2SA1253,(BC308,BC558,..)
2N865	Si-PNP	AF,Sw,10/10/6V,0,05A,0,15W,>24MHz	2a	USA	2SA1246,2SA1253,(BC308,BC558,..)
2N865A	Si-PNP	=2N865:0,1A	2a	Tdy	2SA1246,2SA1253,(BC308,BC558,..)
2N866	Si-NPN	AF-Driver,30V,0,6A,0,5W,>40MHz	2a$	Sty	BC337..338,BC635,BC637,2SD1226..
2N867	Si-NPN	AF-Driver,30V,0,6A,0,5W,>50MHz	2a$	Sty	BC337..338,BC635,BC637,2SD1226..
2N869	Si-PNP	HF/Sw,25V,0,2A,0,36W,300MHz	2a$	USA,Mot,Sgs	BSW24,2N3905..06,2N4125..26
2N869A	Si-PNP	=2N869:>400MHz	2a$	-	BSW24,2N3905..06,2N4125..26
2N87	Ge-PNP	AF-Driver,25V,0,1A,0,2W,0,8MHz	?1e*	Tra	(AC125..126,AC151,2SB56)
2N870	Si-NPN	AF,Sw,100V,0,5W,>50MHz	2a$	USA,Sgs,Tix	BC639,BCX24,2N3700..01,2SD667..
2N871	Si-NPN	=2N870:>60MHz	2a$	USA	BC639,BCX24,2N3700..01,2SD667..
2N876	Thy-50Hz	15V,0,32A(Tc=70°),Igt/Ih<0,2/<5mA	2a$	USA,Tho,Tix	TAG06Y,(2N2322,2N6332,TAG615-100,..)
2N877	Thy-50Hz	=2N876:30V	2a$	-	TAG06Y,(2N2323,2N6332,TAG615-100,..)
2N878	Thy-50Hz	=2N876:60V	2a$	-	TAG06YY,(2N2324,2N6334,TAG615-100,..)
2N879	Thy-50Hz	=2N876:100V	2a$	-	TAG06A,(2N2324,2N6334,TAG615-100,..)
2N88	Ge-PNP	0,025W	37d	Tra	-
2N880	Thy-50Hz	=2N876:150V	2a$	-	TAG06B,(2N2325,2N6335,TAG615-200,..)
2N881	Thy-50Hz	=2N876:200V	2a$	-	TAG06B,(2N2326,2N6335,TAG615-200,..)
2N882	Thy-50Hz	=2N876:300V	2a$	-	TAG06C,(2N2328,2N6336,TAG615-300,..)
2N883	Thy-50Hz	=2N876:400V	2a$	-	TAG06D,(2N2329,2N6337,TAG615-400,..)
2N884	Thy-50Hz	15V,0,32A(Tc=70°),Igt/Ih<0,02/<3mA	2a$	USA,Tho,Tix	(2N2322A)
2N885	Thy-50Hz	=2N884:30V	2a$	-	(2N2323A)
2N886	Thy-50Hz	=2N884:60V	2a$	-	(2N2324A)
2N887	Thy-50Hz	=2N884:100V	2a$	-	(2N2324A)
2N888	Thy-50Hz	=2N884:150V	2a$	-	(2N2325A)
2N889	Thy-50Hz	=2N884:200V	2a$	-	(2N2326A)
2N89	Ge-PNP	0,025W	37d	Tra	-
2N890	Thy-50Hz	=2N884:300V	2a$	-	(2N2328A)
2N891	Thy-50Hz	=2N884:400V	2a$	-	(2N2329A)
2N892	Thy-GTO	15V,0,25A(Tc=70°),Igt/Ih<0,05/<1mA	2a$	USA,Fch	-
2N893	Thy-GTO	=2N892	2a$	-	-
2N894	Thy-GTO	=2N892:30V	2a$	-	-
2N895	Thy-GTO	=2N892:30V	2a$	-	-
2N896	Thy-GTO	=2N892:60V	2a$	-	-
2N897	Thy-GTO	=2N892:60V	2a$	-	-

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2N898	Thy-GTO	=2N892: 100V	2a$	-	-
2N899	Thy-GTO	=2N892: 100V	2a$	-	-
2N90	Ge-PNP	0,025W	37d	Tra	-
2N900	Thy-GTO	=2N892: 200V	2a$	-	-
2N901	Thy-GTO	=2N892: 200V	2a$	-	-
2N902	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >1MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N903	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >2MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N904	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >8MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N905	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >2MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N906	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >2MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N907	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >12MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N908	Si-NPN	AF, Sw, 45V, 0,025A, 0,15W, >25MHz	-	Ray	(BC167, BC182, BC237, 2SC1890,..)
2N909	Si-NPN	GenP, 60V, 1A, 0,5W, >50MHz	2a$	USA, Fch	BC337A, BC637, BC639, BCX24..
2N91	Ge-PNP	AF, Sw, 15V, 0,5A, 0,125W, <1/-µS	?1a*	Tra	AC128, AC152..153, AC188, 2SB405
2N910	SI-NPN	AF, Sw, 100V, 1A, 0,5W, >60MHz	2a$	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667..
2N911	Si-NPN	AF, Sw, 100V, 1A, 0,5W, >50MHz	2a$	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667..
2N912	Si-NPN	AF, Sw, 100V, 1A, 0,5W, >40MHz	2a$	USA, Mot, Sgs	BC639, BCX24, 2N3700..01, 2SD667..
2N913	SI-NPN	VHF, 25V, 0,36W, 350MHz	2a$	Idi, Sca	BF224..225, BF314, BF502..503..
2N914	Si-NPN	Sw, 40V, 0.5A, <40/40nS	-		-
2N914(A)	Si-NPN	Sw, 40V, 0,5A, 0,36W, >300MHz, <40/40nS	2a$	USA, EUR	BSS10, BSX26, BSX39, 2N3261
2N915	Si-NPN	HF/Sw, 70V, 0,36W, >250MHz	2a$	USA, EUR	BSW63..64, 2N2221..22(A), 2SC4648
2N915A	Si-NPN	=2N915: >500MHz	2a$	-	2SC4618, (BSW63..64, 2N2221..22(A))
2N916(A)	Si-NPN	VHF/Sw, 45V, 0,05A, 0,36W, >300MHz	2a$	USA, EUR	BF224..225, BSW63..64, 2N2221..22(A)..
2N9168	Si-NPN	=2N916: 60V, >500MHz	2a$	-	(BF224..225, BSW63..64, 2N2221..22(A)..)
2N917(A)	Si-NPN	VHF/UHF, 30V, 0,05A, 0,2W, 900MHz	Sg	USA, EUR	BF377..378, BF689, BF763, 2N2857..
2N918	Si-NPN	VHF/UHF, 30V, 0,05A, 0,2W, >600MHz	Sg	USA, EUR	BF377..378, BF689, BF763, 2N2857..
2N919	Si-NPN	GenP, 25V, 0,22A, 0,36W, >200MHz, B>20	2a$	Csr, Elc	BC168, BC183, BC238, BC548, 2SD767..
2N92	Ge-PNP	AF, Sw, 25V, 0,2A, 0,125W, <2,5/-µS	?1a*	Tra	AC125..126, AC151, ASY26..27
2N920	Si-NPN	=2N919: B>40	2a$	Csr, Elc, Sgs	BC168, BC183, BC238, BC548, 2SD767..
2N921	SI-NPN	GenP, 50V, 0,2A, 0,36W, 400MHz, B>20	2a$	Csr, Elc	BC167, BC182, BC237, BC547, 2SD767..
2N922	Si-NPN	=2N921: B>40	2a$	Csr, Elc	BC167, BC182, BC237, BC547, 2SD767..
2N923	Si-PNP	GenP, 40/25/40V, 0,05A, 0,15W, a>12	2a$	USA	-
2N924	Si-PNP	=2N923: a>24	2a	USA	-
2N925	Si-PNP	GenP, 50/40/50V, 0,05A, 0,15W, B>10	2a	USA	-
2N926	Si-PNP	GenP, 50/40/50V, 0,05A, 0,15W, B>20	2a	USA	-
2N927	Si-PNP	GenP, 70/60/70V, 0,05A, 0,15W, B>8	2a	USA	-
2N928	SI-PNP	GenP, 70/60/70V, 0,05A, 0,15W, B>18	2a	USA	-
2N929	SI-NPN	GenP, LN, 45V, 0,03A, 0,5W, >30MHz	2a$	USA, EUR	BC414, BC550, 2N2483..84, 2N3117..
2N929A	SI-NPN	=2N929: 60V	2a$	-	BC414, BC550, 2N2483..84, 2N3117..
2N930	Si-NPN	GenP, LN, 45V, 0,03A, 0,5W, >30MHz	2a$	USA, EUR	BC414, BC550, 2N2483..84, 2N3117..
2N930A,B	SI-NPN	=2N929: 60V	2a$	-	BC414, BC550, 2N2483..84, 2N3117..
2N934	Ge-PNP	Sw, 13V, 0,2A, 0,15W, >35MHz	2a	Ray, Sty	2N705, 2N960..967
2N935	SI-PNP	GenP, 50/30/20V, 0,05A, 0,25W, B>9	2a	USA	-
2N936	SI-PNP	GenP, 50/30/20V, 0,05A, 0,25W, B>18	2a	USA	-
2N937	Si-PNP	GenP, 50/30/20V, 0,05A, 0,25W, B>36	2a	USA	-
2N938	Si-PNP	GenP, 40/35/40V, 0,1A, 0,25W, B>9	2a	USA	-
2N939	Si-PNP	GenP, 40/35/40V, 0,1A, 0,25W, B>18	2a	USA	-
2N94(A)	Ge-NPN	HF, 20V, 0,1A, 0,15W, >2MHz, A: >5MHz	?1a	Csr, Etc	ASY28..29, ASY73..75
2N940	Si-PNP	GenP, 40/35/40V, 0,1A, 0,25W, B>36	2a	USA	-
2N941	Si-PNP	Sw, Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	-
2N942	Si-PNP	Sw, Chopper, 25/8/25V, 0,05A, 0,25W	2a	USA	-
2N943	SI-PNP	Sw, Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	-
2N944	Si-PNP	Sw, Chopper, 40/18/40V, 0,05A, 0,25W	2a	USA	-
2N945	Si-PNP	Sw, Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	-
2N946	Si-PNP	Sw, Chopper, 50/50/50V, 0,05A, 0,25W	2a	USA	-
2N947	Si-NPN	Sw, 20V, 0,1A, 0,26W, >200MHz, <35/75nS	2a$	USA	BSY17..18, BSY62..63, 2N706A..
2N948	Thy-50Hz	30V, 0,26A(Tc=125°), Igt/Ih<0,02/<1mA	2a$	USA, Fch	(2N2322A)
2N949	Thy-50Hz	=2N948: 60V	2a$	-	(2N2324A)
2N95(/13)	Ge-NPN	AF, 30V, 1,5A, 2,5W, 0,4MHz	?37	USA	-
2N950	Thy-50Hz	=2N948: 100V	2a$	-	(2N2324A)
2N951	Thy-50Hz	=2N948: 200V	2a$	-	(2N2326A)
2N955	Ge-NPN	UHF, Sw, 12V, 0,1A, 0,15W, 1GHz	2a	Sem	-
2N955A	Ge-NPN	=2N955: 0,5A	2a	-	-
2N956	Si-NPN	AF-Driver, 75V, 0,5W, 300MHz	2a$	USA, EUR	BC639, BCX24, 2N3700..01, 2SD667..

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2N957	Si-NPN	GenP,40V,0,25W,>200MHz	2a$	USA,Fch	BC167,BC182,BC237,BC547,2SD767..
2N958	Si-NPN	GenP,25V,0,2A,0,25W,>200MHz,B>20	24c	Trw	(BC168,BC183,BC238,BC548,..)
2N959	Si-NPN	=2N958:B>40	24c	Trw	(BC168,BC183,BC238,BC548,..)
2N96	Ge-PNP	AF,30V,Ueb=30V,0,02A,0,05W,0,5MHz	?1a	Rca	AC125..126,AC151,ASY26
2N960	Ge-PNP	Sw,15V,0,1A,0,15W,<50/85nS	2a$	USA,Mot,Tix	ASZ21,2N705
2N961	Ge-PNP	Sw,12V,0,1A,0,15W,<50/85nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N962	Ge-PNP	Sw,12V,0,1A,0,15W,<50/100nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N963	Ge-PNP	Sw,12V,0,1A,0,15W,<50/120nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N964(A)	Ge-PNP	Sw,15V,0,1A,0,15W,<50/85nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N965	Ge-PNP	Sw,12V,0,1A,0,15W,<50/85nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N966	Ge-PNP	Sw,12V,0,1A,0,15W,<50/85nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N967	Ge-PNP	Sw,12V,0,1A,0,15W,<60/120nS	2a$	USA,Mot,Tix	ASZ21,2N705(A)
2N968	Ge-PNP	Sw,15V,0,2A,0,15W,320MHz,50/70nS	2a$	USA,Mot	2N705,2N960..967
2N969	Ge-PNP	Sw,12V,0,2A,0,15W,320MHz,50/70nS	2a$	USA,Mot	2N705,2N960..967
2N97(A)	Ge-NPN	AF/HF,30(A:40)V,0,01A,0,05W,1MHz	?1a	USA	(AC127,2SD39)
2N970	Ge-PNP	Sw,12V,0,2A,0,15W,320MHz,65/100nS	2a$	USA,Mot	2N705,2N960..967
2N971	Ge-PNP	Sw,7V,0,2A,0,15W,320MHz,65/100nS	2a$	USA,Mot	2N705,2N960..967
2N972	Ge-PNP	Sw,15V,0,2A,0,15W,320MHz,50/75nS	2a$	USA,Mot	2N705,2N960..967
2N973	Ge-PNP	Sw,12V,0,2A,0,15W,320MHz,50/75nS	2a$	USA,Mot	2N705,2N960..967
2N974	Ge-PNP	Sw,12V,0,2A,0,15W,320MHz,65/100nS	2a$	USA,Mot	2N705,2N960..967
2N975	Ge-PNP	Sw,7V,0,2A,0,15W,320MHz,65/100nS	2a$	USA,Mot	2N705,2N960..967
2N976	Ge-PNP	Sw,15V,0,1A,0,1W,>250MHz	2a	USA	2N705,2N960..967
2N977	Ge-PNP	Sw,15V,0,2A,0,15W,>400MHz	2a	USA	2N705,2N960..967
2N978	Si-PNP	GenP,30V,0,6A,0,33W,>40MHz	2a$	USA,Mot,Sgs	BC327..328,BC636,BC638,2SA1515..
2N979	Ge-PNP	Sw,20/15V,0,1A,0,06W,>100MHz	2a	USA	ASZ21,2N705,2N960..967
2N98(A)	Ge-NPN	AF/HF,40V,0,01A,0,05W,2,5MHz	?1a	USA	(AC127,2SD39)
2N980	Ge-PNP	=2N979:20/12V	2a	USA	ASZ21,2N705,2N960..967
2N981	Si-NPN	GenP,80V,0,1A,0,5W,>50MHz	2a$	USA,Nsc	BC546,2SC1890(A),2SC2240,2SC2459..
2N982	Ge-PNP	Sw,20V,0,1A,0,06W,450MHz	2a$	USA	ASZ21,2N705,2N960..967
2N983	Ge-PNP	=2N982:15V	2a$	USA	ASZ21,2N705,2N960..967
2N984	Ge-PNP	=2N982:15V	2a$	USA	ASZ21,2N705,2N960..967
2N985	Ge-PNP	Sw,15V,0,2A,0,15W,>300MHz,<35/80nS	2a$	USA,Mot	2N705,2N960..967
2N986	Opto	-	-	-	-
2N987	Ge-PNP	HF,40V,10mA,0,1W,>40MHz	5g	USA	AF124..126,AF200
2N988	Si-NPN	GenP,20V,0,22A,0,3W,>300MHz	2a$	USA	BC168,BC183,BC238,BC548,2SD767..
2N989	Si-NPN	GenP,20V,0,22A,0,3W,>300MHz	2a$	USA	BC168,BC183,BC238,BC548,2SD767..
2N99	Ge-NPN	AF/HF,40V,0,01A,0,05W,3,5MHz	?1a	USA	(AC127,2SD39)
2N990	Ge-PNP	HF,20V,10mA,0,067W,>44MHz	5k	USA	AF124..126,AF200
2N991	Ge-PNP	HF,20V,10mA,0,067W,>44MHz	5k	USA	AF124..126,AF200
2N992	Ge-PNP	HF,20V,10mA,0,067W,>44MHz	5k	USA	AF124..126,AF200
2N993	Ge-PNP	HF,20V,10mA,0,067W,>44MHz	5k	USA	AF124..126,AF200
2N994	Ge-PNP	Sw,15V,0,15A,0,2W,<35/45nS	2a$	USA	2N705,2N960..967
2N995(A)	Si-PNP	GenP,20V,0,36W,300MHz,A:<60/90nS	2a$	USA,Mot,Sgs	BC308,BC558,2N3209,2N4125..26..
2N996	Si-PNP	GenP,15V,0,2A,0,36W,>100MHz	2a$	USA,Mot	BC213,BC258,BC308,BC558,2SB725..
2N997	Si-NPN-Darl	GenP,75V,0,3A,0,5W,B>4000	5r$	USA,Mot,Sgs	BFX66
2N998	Si-NPN-Darl	GenP,100V,0,5A,0,5W,B>1600	5r$	USA,Mot,Sgs	BFX66
2N999	Si-NPN-Darl	GenP,60V,0,5A,0,5W,B>4000	5r$	USA,Mot,Sgs	BFX67
2P05M	Thy-50Hz	50V,2A(Tc=54°),Igt/Ih<0,2/<3mA	13h$	NEC	C106F1,TAG106F,C108F,TAG108F..
2P1M	Thy-50Hz	=2P05M:100V	13h$	-	C106A1,TAG106A,C108A,TAG108A..
2P2M	Thy-50Hz	=2P05M:200V	13h$	-	C106B1,TAG106B,C108B,TAG108B..
2P4M	Thy-50Hz	=2P05M:400V	13h$	-	C106D1,TAG106D,C108D,TAG108D..
2P5M	Thy-50Hz	=2P05M:500V	13h$	-	C106E1,TAG106E,C108E,TAG108E..
2P6M	Thy-50Hz	=2P05M:600V	13h$	-	C106M1,TAG106M,C108M,TAG108M..
2PA1015(L)	Si-PNP	=2SA1015(L):0,5W	7c	Phi	→2SA1015(L)
2PA1774	Si-PNP	=2SA1774	35a(1,6mm)	Phi	→2SA1774
2PA733P	Si-PNP	=2SA733:0,5W	7c	Phi	→2SA733
2PB1219Q	Si-PNP	-	35(2mm)	Phi	→2PB1219
2PB1219R	Si-PNP	-	35(2mm)	Phi	→2PB1219
2PB1219S	Si-PNP	-	35(2mm)	Phi	→2PB1219
2PB709(A)	Si-PNP	=2SB709(A)	35a	Phi	→2SB709(A)
2PB709AQ	Si-PNP	PNP 45V0.1Ahfe 160-260	35	Phi	→2PB709A
2PB709AR	Si-PNP	pnp45V0.1Ahfe210-340	35	Phi	→2PB709A
2PB709AS	Si-PNP	pnp 45V0.1Ahfe 290-460	35	Phi	→2PB709A
2PB709Q	Si-PNP	-	35	Phi	→2PB709

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2PB709R	Si-PNP	-	35	Phi	→2PB709
2PB709S	Si-PNP	-	35	Phi	→2PB709
2PB710A	Si-PNP	=2SB710A	35a(2mm)	Phi	→2SB710A
2PB710AQ	Si-PNP	-	35	Phi	→2PB710A
2PB710AR	Si-PNP	-	35	Phi	→2PB710A
2PB710AS	Si-PNP	-	35	Phi	→2PB710A
2PB710Q	Si-PNP	-	35	Phi	→2PB710
2PB710R	Si-PNP	-	35	Phi	→2PB710
2PB710S	Si-PNP	-	35	Phi	→2PB710
2PC1815(L)	Si-NPN	=2SC1815(L):0,5W	7c	Phi	→2SC1815(L)
2PC945	Si-NPN	=2SC945:0,5W	7c	Phi	→2SC945
2PD1820A	Si-NPN	→2SD1820A	35a(2mm)	Phi	→2SD1820A
2PD1820AQ	Si-NPN	gp sw amp 50V npn hfe 85-170	35(2mm)	Phi	→2PD1820A
2PD1820-AQ	Si-NPN	gp sw amp 50V npn hfe 85-170	-	Phi	-
2PD601(A)	Si-NPN	→2SD601(A)	35a	Phi	→2SD601(A)
2PD601AQ	Si-NPN	-	35	Phi	→2PD601A
2PD601AR	Si-NPN	-	35	Phi	→2PD601A
2PD601AS	Si-NPN	-	35	Phi	→2PD601A
2PD601Q	Si-NPN	-	35	Phi	→2PD601
2PD601R	Si-NPN	-	35	Phi	→2PD601
2PD601S	Si-NPN	-	35	Phi	→2PD601
2PD602A	Si-NPN	→2SD602A	35a	Phi	→2SD602A
2PD602AQ	Si-NPN	-	35	Phi	→2PD602A
2PD602AR	Si-NPN	-	35	Phi	→2PD602A
2PD602AS	Si-NPN	-	35	Phi	→2PD602A
2PD602Q	Si-NPN	-	35	Phi	→2PD602
2PD602R	Si-NPN	-	35	Phi	→2PD602
2PD602S	Si-NPN	-	35	Phi	→2PD602
2S014	Si-NPN	HF, 40V, 20mA, >10MHz	2a$	TI	BC167, BC183, BC237, BC547..
2S017	Si-NPN	GenP, 60V, 0,4A, >2,5MHz	2a$	TI	BC140..141, BC300..302, 2N3053..
2S018	Si-NPN	GenP, 100V, 0,4A, >2,5MHz	2a$	TI	BC141, BC300, 2N1889..90, 2N1990..
2S019	Si-NPN	GenP, 60V, 0,4A, >2,5MHz	2a$	TI	BC140..141, BC300..302, 2N3053..
2S020	Si-NPN	GenP, 100V, 0,4A, >2,5MHz	2a$	TI	BC141, BC300, 2N1889..90, 2N1990..
2S024	Si-NPN	AF/HF/Sw-Pow, 100V, 75A, 100W, 12MHz	-	TI	-
2S025	Si-NPN	=2S024:150V	-	TI	-
2S026	Si-NPN	=2S024:200V	-	TI	-
2S033(A)	Si-NPN	AF, 5w-Pow, 100V, 3A, 40W, 25MHz, B>30	23a$	TI	BD245C, BDX95, 2N5758..60, 2SD895..
2S034	Si-NPN	=2S033:B>60	23a$	TI	BD245C, BDX95, 2N5758..60, 2SD896..
2S035	Si-NPN	=2S033:150V	23a$	TI	BD245D, 2SD731..732, 2SC2260..62..
2S036	Si-NPN	=2S033:150V, B>60	23a$	TI	BD245D, 2SD731..732, 2SC2260..62..
2S100	Ge-PNP	→2SB100	-	JAP	-
2S101	Ge-PNP	→2SB101	-	JAP	-
2S102	Ge-PNP	→2SB102	-	JAP	-
2S102	Si-NPN	Sw, 60V, 0,05A, 0,4W, >150MHz, B>20	2a$	TI	BC182, BC190, BC546, 2N3903..04..
2S103	Si-NPN	=2S102:B>40	2a$	TI	BC182, BC190, BC546, 2N3903..04..
2S103	Ge-PNP	→2SB103	-	JAP	-
2S104	Si-NPN	=2S102:B>80	2a$	TI	BC182, BC190, BC546, 2N3903..04..
2S104	Ge-PNP	→2SB104	-	JAP	-
2S105	Ge-PNP	→2SB105	-	JAP	-
2S106	Ge-PNP	→2SB106	-	JAP	-
2S107	Ge-PNP	→2SB107	-	JAP	-
2S108	Ge-PNP	→2SA108	-	JAP	-
2S109	Ge-PNP	→2SA109	-	JAP	-
2S11	Ge-PNP	→2SB66	-	JAP	-
2S110	Ge-PNP	→2SA110	-	JAP	-
2S111	Ge-PNP	→2SA111	-	JAP	-
2S112	Ge-PNP	→2SA112	-	JAP	-
2S113	Ge-PNP	→2SB12	-	JAP	-
2S114	Ge-PNP	→2SB13	-	JAP	-
2S115	Ge-PNP	→2SB14	-	JAP	-
2S116	Ge-PNP	→2SB15	-	JAP	-
2S119	Ge-PNP	→2SB16	-	JAP	-
2S120	Ge-PNP	→2SB17	-	JAP	-
2S121	Ge-PNP	→2SB18	-	JAP	-

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2S122	Ge-PNP	→2SB19	-	JAP	-
2S123	Ge-PNP	→2SB20	-	JAP	-
2S124	Ge-PNP	→2SB21	-	JAP	-
2S125	Ge-PNP	→2SB22	-	JAP	-
2S126	Ge-PNP	→2SB23	-	JAP	-
2S131	Ge-PNP	→2SB131	-	JAP	-
2S131	Si-NPN	Fast-Sw, 15V, 0,2A, 0,3W, >220MHz	2a$	TI	BSS11..12, BSY17..18, 2N2368..69(A),..
2S132	Ge-PNP	→2SC73	-	JAP	-
2S133	Ge-PNP	→2SC75	-	JAP	-
2S134	Ge-PNP	→2SC76	-	JAP	-
2S135	Ge-PNP	→2SC77	-	JAP	-
2S136	Ge-PNP	→2SC78	-	JAP	-
2S138	Ge-PNP	→2SA124	-	JAP	-
2S139	Ge-PNP	→2SA125	-	JAP	-
2S140	Ge-PNP	→2SA80	-	JAP	-
2S141	Ge-PNP	→2SA81	-	JAP	-
2S142	Ge-PNP	→2SA82	-	JAP	-
2S143	Ge-PNP	→2SA83	-	JAP	-
2S144	Ge-PNP	→2SA84	-	JAP	-
2S145	Ge-PNP	→2SA85	-	JAP	-
2S148	Ge-PNP	→2SB74	-	JAP	-
2S150	Ge-PNP	→2SB150	-	JAP	-
2S153	Ge-PNP	→2SA153	-	JAP	-
2S154	Ge-PNP	→2SA154	-	JAP	-
2S155	Ge-PNP	→2SA155	-	JAP	-
2S156	Ge-PNP	→2SA156	-	JAP	-
2S157	Ge-PNP	→2SA157	-	JAP	-
2S158	Ge-PNP	→2SA158	-	JAP	-
2S159	Ge-PNP	→2SA159	-	JAP	-
2S160	Ge-PNP	→2SA160	-	JAP	-
2S161	Ge-PNP	→2SB161	-	JAP	-
2S162	Ge-PNP	→2SB162	-	JAP	-
2S163	Ge-PNP	→2SB163	-	JAP	-
2S164	Ge-PNP	→2SB164	-	JAP	-
2S165	Ge-PNP	→2SB165	-	JAP	-
2S166	Ge-PNP	→2SB166	-	JAP	-
2S167	Ge-PNP	→2SA167	-	JAP	-
2S168	Ge-PNP	→2SA168	-	JAP	-
2S169	Ge-PNP	→2SA169	-	JAP	-
2S170	Ge-PNP	→2SA170	-	JAP	-
2S171	Ge-PNP	→2SA171	-	JAP	-
2S172	Ge-PNP	→2SA172	-	JAP	-
2S173	Ge-PNP	→2SA173	-	JAP	-
2S174	Ge-PNP	→2SA174	-	JAP	-
2S175	Ge-PNP	→2SA175	-	JAP	-
2S176	Ge-PNP	→2SA176	-	JAP	-
2S177	Ge-PNP	→2SB80..82	-	JAP	-
2S179	Ge-PNP	→2SB179	-	JAP	-
2S188	Ge-PNP	→2SB188	-	JAP	-
2S189	Ge-PNP	→2SB189	-	JAP	-
2S190	Ge-PNP	→2SA86	-	JAP	-
2S191	Ge-PNP	→2SA41	-	JAP	-
2S192	Ge-PNP	→2SA42	-	JAP	-
2S193	Ge-PNP	→2SB67	-	JAP	-
2S26(A)	Ge-PNP	→2SB25..26	-	JAP	-
2S2M	Thy-Fast	200V, 2A(Tc=54°), Igt/Ih<0,3/<10mA	13h$	NEC	-
2S30	Ge-PNP	→2SA30	-	JAP	-
2S301	Si-PNP	GenP, 80V, 0,1A, 0,3W	2a$	TI	BC303, BC556, 2SA970, 2SA1285(A)..
2S3010	Si-PNP	GenP, 40V, 0,15A, 0,3W	2a$	TI	BC303..304, BC307, BC557, 2N2303..
2S302	Si-PNP	=2S301: 40V	2a$	-	BC303..304, BC307, BC557, 2N2303..
2S3020	Si-PNP	GenP, 40V, 0,15A, 0,3W	2a$	TI	BC303..304, BC307, BC557, 2N2303..
2S3021	Si-PNP	GenP, 15V, 0,15A, 0,3W	2a$	TI	BC303..304, BC308, BC558, 2N2303..
2S302A	Si-PNP	=2S301: 25V	2a$	-	BC303..304, BC308, BC558, 2N2303..
2S303	Si-PNP	=2S301: 25V	2a$	-	BC303..304, BC308, BC558, 2N2303..

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2S3030	Si-PNP	GenP,25V,0,15A,0,3W	2a$	TI	BC303..304,BC308,BC558,2N2303..
2S304	Si-PNP	=2S301:15V	2a$	-	BC303..304,BC308,BC558,2N2303..
2S3040	Si-PNP	GenP,15V,0,15A,0,3W	2a$	TI	BC303..304,BC308,BC558,2N2303..
2S305	Si-PNP	=2S301:125V	2a$	-	BF398,2SA970,2SA1049,2SA1285(A)..
2S306	Si-PNP	GenP,sym,6/6/6V,10mA,0,05W	2a$	TI	-
2S307	Si-PNP	=2S306:15/15/15V	2a$	-	-
2S31	Ge-PNP	→2SA31	-	JAP	-
2S32	Ge-PNP	→2SB32	-	JAP	-
2S321	Si-PNP	=2S301	2a	TI	→2S301
2S322(A)	Si-PNP	=2S302(A)	2a	-	→2S302(A)
2S3220	Si-PNP	=2S3020	2a	TI	→2S3020
2S3221	Si-PNP	=2S3021	2a	-	→2S3021
2S323	Si-PNP	=2S303	2a	-	→2S303
2S3230	Si-PNP	=2S3030	2a	-	→2S3030
2S324	Si-PNP	=2S304	2a	-	→2S304
2S3240	Si-PNP	=2S3040	2a	-	→2S3040
2S325	Si-PNP	=2S305	2a	-	→2S305
2S326	Si-PNP	=2S306	2a	TI	-
2S327	Si-PNP	=2S307	2a	-	-
2S35	Ge-PNP	→2SA35	-	JAP	-
2S36	Ge-PNP	→2SA36	-	JAP	-
2S39	Ge-PNP	→2SB39	-	JAP	-
2S3M	Thy-Fast	=2S3M:300V	13h$	-	-
2S41	Ge-PNP	→2SB41	-	JAP	-
2S42	Ge-PNP	→2SB42	-	JAP	-
2S43	Ge-PNP	→2SA43	-	JAP	-
2S44	Ge-PNP	→2SB44	-	JAP	-
2S45	Ge-PNP	→2SA45	-	JAP	-
2S46	Ge-PNP	→2SB46	-	JAP	-
2S47	Ge-PNP	→2SB47	-	JAP	-
2S48	Ge-PNP	→2SA48	-	JAP	-
2S49	Ge-PNP	→2SA49	-	JAP	-
2S4M	Thy-Fast	=2S2M:400V	13h$	-	-
2S50	Ge-PNP	→2SA50	-	JAP	-
2S501	Si-NPN	GenP,25V,0,03A,0,3W,>30MHz,B>40	2a$	TI	BC168,BC183,BC238,BC548..
2S502	Si-NPN	=2S501:B>100	2a$	-	BC168,BC183,BC238,BC548..
2S503	Si-NPN	=2S501:B>180	2a$	-	BC168,BC183,BC238,BC548..
2S51	Ge-PNP	→2SA51	-	JAP	-
2S512	Si-NPN	Sw,25V,0,2A,0,3W,>250MHz	2a$	TI	BSS11..12,BSX19..20,2N2368..69(A),..
2S52	Ge-PNP	→2SA52	-	JAP	-
2S53	Ge-PNP	→2SA53	-	JAP	-
2S54	Ge-PNP	→2SB54	-	JAP	-
2S56(A)	Ge-PNP	→2SB55..56,2SB94	-	JAP	-
2S57	Ge-PNP	→2SA57	-	JAP	-
2S58	Ge-PNP	→2SA58	-	JAP	-
2S59	Ge-PNP	→2SA59	-	JAP	-
2S60	Ge-PNP	→2SA27	-	JAP	-
2S60A	Ge-PNP	→2SA60	-	JAP	-
2S61	Ge-PNP	→2SB61	-	JAP	-
2S64	Ge-PNP	→2SA64	-	JAP	-
2S65	Ge-PNP	→2SB65	-	JAP	-
2S721	Si-NPN	AF,Sw-Pow,60V,2A,150W,>2MHz,B>20	-	TI	(BD245A,BDV91,2SD718,2SD895..896..)
2S722	Si-NPN	=2S721:100V	-		(BD245C,BDV93,2SD718,2SD895..896..)
2S723	Si-NPN	=2S721:B>40	-		(BD245A,BDV91,2SD718,2SD895..896..)
2S724	Si-NPN	=2S721:100V,B>40	-		(BD245C,BDV93,2SD718,2SD895..896..)
2S74	Ge-PNP	→2SB173	-	JAP	-
2S91	Ge-PNP	→2SB79	-	JAP	-
2S92	Ge-PNP	→2SA28	-	JAP	-
2S92A	Ge-PNP	→2SA92	-	JAP	-
2S93	Ge-PNP	→2SA29	-	JAP	-
2S93A	Ge-PNP	→2SA93	-	JAP	-
2S95	Ge-PNP	→2SA95	-	JAP	-
2S95A	Si-NPN	Fast-Sw,25V,0,2A,0,3W,>300MHz	2a$	TI	BSS11..12,BSX19..20,2N2368..69(A),..
2S96	Ge-PNP	→2SA96	-	JAP	-

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2S97	Ge-PNP	→2SA97	-	JAP	-
2S98	Ge-PNP	→2SA98	-	JAP	-
2S99	Ge-PNP	→2SA99	-	JAP	-
2SA100	Ge-PNP	HF/AF,40V,10mA,20MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA1001	Si-PNP	AF,Sw-Pow,130V,8A,80W,40MHz	23a$	Fui	2SA908,2SA1386(A),2SB555,2SB681..
2SA1002	Si-PNP	AF,Sw-Pow,120V,12A,120W,40MHz	23a$	Fui	2SA908,2SA1386(A),2SB555,2SB681..
2SA1003	Si-PNP	=2SA1002:150V	23a$	-	2SA908,2SA1386(A),2SB697,2SB681..
2SA1004	Si-PNP	GenP,40V,0,1A,0,31W,200MHz	7e	Hit	BC213,BC257,BC307,BC557..
2SA1005	Si-PNP	FM-Tuner,HF,40V,,0,03A,0,25W,400MHz	7c	Nec	BF324,BF414,BF936,BF939,BF509
2SA1006	Si-PNP	AF/HF-Pow,180V,1,5A,25W,80MHz	17j$	Nec	2SA968A,B,2SA1009(A),2SA1133,2SB628A
2SA1006A	Si-PNP	=2SA1006:200V	17j$	-	2SA968B,2SA1009(A),2SA1133
2SA1006B	Si-PNP	=2SA1006:250V	17j$	-	2SA1009(A),2SA1236,2SA1397
2SA1007(A)	Si-PNP	AF,Sw-Pow,150V,10A,100W,50MHz	23a$	Nec	BDX20,2SA1386(A),2SB681,2SB697..
2SA1008	Si-PNP	Sw,Pow,100V,2A,15W,<0,5/2µS	17j$	Nec	2SA1078..1079,2SB719..720,2SB861,+
2SA1009	Si-PNP	Sw,Pow,350/350V,2A,15W,<1/3,5µS	17j$	Nec	2SA1236,2SA1397
2SA1009A	Si-PNP	=2SA1009:400/400V	17j$	-	2SA1236,2SA1397
2SA101	Ge-PNP	HF/AF,40V,10mA,15MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA1010	Si-PNP	Sw,Pow,100V,7A,40W,<0,5/2µS	17j$	Nec	BD244C,BD544C,MJE15029,TIP42C,2SA1077..
2SA1011	Si-PNP	AF,Sw-Pow,180V,1,5A,25W,100MHz	17j$	Sanyo	2SA968A,B,2SA1112,2SA1133,2SB628A
2SA1012	Si-PNP	Sw,Pow,Lo-sat,60V,5A,25W,60MHz	17j$	Tos	2SA1289..1291,2SA1293,2SB919,TIP42A
2SA1013	Si-PNP	CTV-AF/VD,160V,1A,0,9W,>15MHz	7c(9mm)	Tos	2SA1275,2SB1212,2SB1236A
2SA1014	Si-PNP	=2SA1013:10W	13g$	Tos	(2SA913A,2SA1112,2SB630,2SB861)
2SA1015	Si-PNP	GenP,50V,0,15A,0,4W,>80MHz	7c	Tos	BC212,BC257,BC307,BC557..
2SA1016	Si-PNP	GenP,LN,120V,0,05A,0,4W,110MHz	7c	Sanyo	2SA941,2SA970,2SA992,2SA1038..
2SA1016K	Si-PNP	=2SA1016:150V	7c	-	2SA1123..24
2SA1017	Si-PNP	AF-Driver,120V,0,05A,0,5W,110MHz	7c	Sanyo	2SA893A,2SA1019,2SA1285,2SB716(A)..
2SA1018	Si-PNP	Vid,250/200V,0,07A,0,75W,>50MHz	7c	Mat	BF423,BF436..437,2SA1371..1372..
2SA1019	Si-PNP	AF-Driver,150V,0,05A,0,9W,110MHz	7c(9mm)	Sanyo	2SA1124,2SA1281,2SA1285A,2SB1348
2SA102	Ge-PNP	HF/AF,40V,10mA,25MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA1020	Si-PNP	AF,Sw,50V,2A,0,9W,100MHz	7c(9mm)	Tos	2SA1382,2SA1315,2SB892,2SB1312,TIP32A…
2SA1021	Si-PNP	TV-VD,150V,1,5A,20W,>15MHz	14h$	Tos	2SA1249,2SB649
2SA1022	Si-PNP	LN,30V,0,03A,>150MHz	35a	Mat	BC859..860,BCF30,BCF70,BF550
2SA1022-A	Si-PNP	-	35	Mat	→2SA1022
2SA1022-B	Si-PNP	-	35	Mat	→2SA1022
2SA1022-C	Si-PNP	-	35	Mat	→2SA1022
2SA1023	Si-PNP	GenP,70V,0,1A,0,25W,180MHz	7c	Nec	BC556,2SA970,2SA1049,2SA1285(A)..
2SA1024	Si-PNP	Sw,400V,0,1A,0,4W,15MHz	2a	Hit	2SA1251,2SA1372,2SB1074
2SA1025	Si-PNP	GenP,60V,0,1A,0,4W,90MHz	7c	Hit	BC212,BC256,BC266,BC556..
2SA1026	Si-PNP	GenP,50V,0,2A,0,25W,100MHz	10b	Mit	BC212,BC256,BC266,BC556..
2SA1027	Si-PNP	GenP,LN,50V,0,2A,0,25W,100MHz	10b	Mit	BC214,BC416,BC560,2SA1136..1137,..
2SA1028	Si-PNP	AF,Sw-Pow,100V,10A,95W,60MHz	23a$	Son	2SA1141,2SA1146,2SA1186
2SA1029	Si-PNP	GenP,30V,0,1A,0,2W,280MHz	7c	Hit	BC213,BC258,BC308,BC558..
2SA103	Ge-PNP	HF/AF,40V,10mA,35MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA1030	Si-PNP	=2SA1029:55V	7c	Hit	BC212,BC257,BC307,BC557..
2SA1031	Si-PNP	=2SA1029:ra	7c	Hit	BC214,BC259,BC309,BC559,2SA1137+
2SA1032	Si-PNP	=2SA1029:55V,ra	7c	Hit	BC214,BC416,BC560,2SA1136..1137,..
2SA1033	Si-PNP	GenP,30V,0,1A,0,31W,280MHz	7e	Hit	BC213,BC258,BC308,BC558..
2SA1034	Si-PNP	LN,35V,0,05A,200MHz	35a	Mat	BC859..860,BCF29..30,BCF70,2SA1312
2SA1034-R	Si-PNP	-	35	Mat	→2SA1034
2SA1034-S	Si-PNP	-	35	Mat	→2SA1034
2SA1034-T	Si-PNP	-	35	Mat	→2SA1034
2SA1035	Si-PNP	-	35	Mat	→2SA1035
2SA1035-R	Si-PNP	-	35	Mat	→2SA1035
2SA1035-S	Si-PNP	-	35	Mat	→2SA1035
2SA1035-T	Si-PNP	-	35	Mat	→2SA1035
2SA1037	Si-PNP	50V,0.4A,140MHz	-		-
2SA1037(A,K,KLN)	Si-PNP	LN,50V,0,1A,140MHz	?35a,35a	Rhm	BC860,BCF70
2SA1037F-Q	Si-PNP	-	?35	Rhm	→2SA1037
2SA1037F-R	Si-PNP	-	?35	Rhm	→2SA1037
2SA1037F-S	Si-PNP	-	?35	Rhm	→2SA1037
2SA1037KLN-E	Si-PNP	-	35	Rhm	→2SA1037KLN
2SA1037KLN-R	Si-PNP	-	35	Rhm	→2SA1037KLN
2SA1037KLN-S	Si-PNP	-	35	Rhm	→2SA1037KLN
2SA1037K-Q	Si-PNP	-	35	Rhm	→2SA1037K

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2SA1037K-R	Si-PNP	-	35	Rhm	→2SA1037K
2SA1037K-S	Si-PNP	-	35	Rhm	→2SA1037K
2SA1038	Si-PNP	GenP,LN,120V,0,05A,0,3W,140MHz	7c	Rhm	2SA941,2SA970,2SA992,2SA1136..
2SA1039	Si-PNP	=2SA1038:80V	7c	Rhm	2SA942,2SA970,2SA992,2SA1136..37..
2SA104	Ge-PNP	HF/AF,40V,10mA,50MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA1040	Si-PNP	Sw,Pow,120V,10A,100W,60MHz	23a$	Fui	BUW96,2SA1146,2SA1186,2SB552
2SA1041	Si-PNP	Sw,Pow,120V,15A,100W,60MHz	23a$	Fui	BUW96,2SA908..909,2SA1147,2SB552
2SA1042	Si-PNP	Sw,Pow,70V,15A,100W,60MHz	23a$	Fui	BUW96,2SA907..909,2SA1147,2SB552
2SA1043	Si-PNP	Sw,Pow,120V,30A,150W,60MHz	23a$	Fui	-
2SA1044	Si-PNP	=2SA1043:70V	23a$	Fui	-
2SA1045	Si-PNP-Darl	Sw,Pow,100V,10A,100W,B=3000	23a$	Fujitsu	BDX64B,BDX84C,BDX88C,MJ4032,2SB693..
2SA1046	Si-PNP-Darl	=2SA1045:15A	23a$	Fui	BDX66B,BDX88C,MJ4032,2SB693
2SA1047	Si-PNP	AF-Dr-Pow,160V,0,08A,130MHz	14h$	Sanyo	BF416,BF418,BF470,BF472,2SB1109+
2SA1048	Si-PNP	GenP,LN,50V,0,15A,0,2W,>80MHz	41c	Tos	BC214,BC416,BC560,2SA1136..1137,..
2SA1049	Si-PNP	GenP,120V,0,1A,0,2W,100MHz	41c	Tos	2SA970,2SA992,2SA1136,2SA1285..
2SA105	Ge-PNP	AM-Amp,6V,10mA,75MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1050	Si-PNP	AF,Sw-Pow,140V,12A,100W,70MHz	23a$	Tos	2SA1227,2SA1386,2SB555,2SB681..
2SA1050A	Si-PNP	=2SA1050:120W	23a$	-	2SA1227,2SA1386,2SB555,2SB681..
2SA1051	Si-PNP	AF,Sw-Pow,150V,15A,150W,60MHz	23a$	Tos	MJ15016,2SA908..09,2SA1117,2SA1147..
2SA1051A	Si-PNP	=2SA1051:160V	23a$	-	MJ15016,2SA909,2SA1116..17,2SA1147..
2SA1052	Si-PNP	30V,0,1A,280MHz	35a	Hit	BC856..858,BCW29..30,BCW69..70..
2SA1052-B	Si-PNP	-	35	Hit	→2SA1052
2SA1052-C	Si-PNP	-	35	Hit	→2SA1052
2SA1052-D	Si-PNP	-	35	Hit	→2SA1052
2SA1053	Si-PNP	Sw,40V,0,2A,0,6W,<70/300nS	7e	Nec	BSW24,2N3250..51(A),2N3905..06..
2SA1054	Si-PNP	Sw,60V,0,6A,0,6W,<35/225nS	7e	Nec	BSW24,2N2906..07(A),2N4026..29
2SA1055	Si-PNP	Sw,25V,0,2A,0,6W,<70/300nS	7e	Nec	BSW24,2N3905..06,2N4125..26..
2SA1056	Si-PNP	Sw,40V,0,6A,0,6W,<35/225nS	7e	Nec	BSW24,2N2906..07(A),2N4026..29..
2SA1057	Si-PNP	UHF,20V,0,05A,4GHz	52s	Nec	BFQ32,2SA801,2SA1223
2SA1058	Si-PNP	UHF,20V,0,05A,2,5GHz	52s	Nec	BFQ32,BFQ78,2SA801,2SA1223
2SA1059	Si-PNP	Dual,Sw,20V,0,03A,0,3W,<10/10nS	-	Nec	-
2SA106	Ge-PNP	AM-Mix/Osc,6V,10mA,30MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1060	Si-PNP	AF,Sw-Pow,80V,5A,60W,15MHz	18j$	Mat	BD246B,2SB688,2SB776,2SB816..
2SA1061	Si-PNP	AF,Sw-Pow,100V,6A,70W,15MHz	18j$	Mat	BD246C,2SB688,2SB776,2SB816..
2SA1062	Si-PNP	AF,Sw-Pow,120V,7A,80W,15MHz	18j$	Mat	BD246C,2SB688,2SB776,2SB816..
2SA1063	Si-PNP	AF,Sw-Pow,150V,6A,80W,50MHz	23a$	Mat	2SA1186,2SB681,2SB696..697,2SB816,MJ2955…
2SA1064	Si-PNP	AF,Sw-Pow,150V,8A,100W,50MHz	23a$	Mat	2SA1186,2SB681,2SB697,2SB817..
2SA1065	Si-PNP	AF,Sw-Pow,150V,10A,120W,50MHz	23a$	Mat	2SA1186,2SB681,2SB697,2SB817..
2SA1066	Si-PNP	GenP,70V,0,2A,0,5W,120MHz	7c	Son	BC556,2SA970,2SA941..942,2SA1285..
2SA1067	Si-PNP	AF,Sw-Pow,120V,10A,100W,50MHz	23a$	Sak	2SA1186,2SB681,2SB697,2SB817..
2SA1068	Si-PNP	=2SA1067:150V	23a$	Sak	2SA1186,2SB681,2SB697,2SB817..
2SA1069(A)	Si-PNP	Sw,Pow,80V,5A,30W,<0,5/3µS	17j$	Nec	BD244B,BD540B,BD952,2SA1289..90,..
2SA107	Ge-PNP	AM-IF,9V,10mA,40MHz	4g	Fui	AF124..127,AF200,2SA218..227
2SA1072	Si-PNP	AF,Sw-Pow,120V,12A,120W,60MHz	23a$	Fui	2SA1227,2SA1386,2SB555,2SB681..
2SA1072A	Si-PNP	=2SA1072:150V	23a$	-	2SA1227A,2SA1386,2SB697,2SB681..
2SA1073	Si-PNP	=2SA1072:160V	23a$	Fui	2SA1227A,2SA1386,2SB697,2SB681..
2SA1074	Si-PNP	AF,Sw-Pow,160V,15A,150W	23a$	Fui	MJ15016,2SA908..09,2SA1117,2SA1147..
2SA1075	Si-PNP	=2SA1072:	20j$	Fui	2SA1094..1095,2SA1166,2SA1187..
2SA1076	Si-PNP	=2SA1073:	20j$	Fui	2SA1095,2SA1166,2SA1215,2SA1389..
2SA1077	Si-PNP	DC-DCConverter,120V,10A,60W,60MHz	17j$	Fui	-
2SA1078	Si-PNP	AF,Sw-Pow,120V,2A,25W,140MHz	17j$	Fui	2SA1133,2SB719..720
2SA1079	Si-PNP	=2SA1078:160V	17j$	Fui	2SA1133,2SB719..720
2SA108	Ge-PNP	AM-Amp,20V,10mA,50MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1080	Si-PNP	AF,Sw-Pow,40V,0,5A,20W,30MHz	17j$	Fui	BD240,2SA748
2SA1081	Si-PNP	GenP,90V,0,1A,0,4W,90MHz	7c	Hit	2SA970,2SA1049,2SA1136,2SA1285(A)
2SA1082	Si-PNP	=2SA1081:120V	7c	Hit	2SA970,2SA1049,2SA1136,2SA1285(A)
2SA1083	Si-PNP	=2SA1081:ra,60V	7c	Hit	BC416,BC560,2SA970,2SA1049..
2SA1084	Si-PNP	=2SA1081:ra,90V	7c	Hit	2SA970,2SA1049,2SA1136
2SA1085	Si-PNP	=2SA1081:ra,120V	7c	Hit	2SA970,2SA1049,2SA1136
2SA109	Ge-PNP	AM-Amp,20V,10mA,45MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1090	Si-PNP	HF/Sw,60V,0,2A,0,3W,250MHz	2a$	Tos	BC212,BC556,2N2906..2907(A)..
2SA1091	Si-PNP	Vid,300V,0,1A,0,4W,60MHz	7c	Tos	BF437,BF421A,2SA1371..1372..
2SA1092	Si-PNP	GenP,LN,60V,0,05A,0,25W,220MHz	7c	Mat	BC416,BC560,2SA970,2SA1136..1137,..
2SA1093	Si-PNP	AF/HF/Sw-Pow,120V,8A,80W,90MHz	18j$	Tos	2SA1141,2SA1146,2SA1186

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2SA1094	Si-PNP	AF,Sw-Pow,140V,12A,120W,70MHz	20j$	Tos	2SA1076,2SA1166,2SA1187,2SA1389..
2SA1095	Si-PNP	=2SA1094:160V,15A,150W,60MHz	20j$	Tos	2SA1076,2SA1166(A),2SA1215,2SA1389,..
2SA1096(A)	Si-PNP	AF,Sw-Pow,70V,2A,5W,150MHz	14h$	Mat	BD378,BD380,2SB744(A),2SB874..75,..
2SA1097(-1,-2)	Si-PNP	AF,Sw-Pow,100..130V,10A,95W,60MHz	-	Son	BD246C,2SA1141,2SA1146,2SA1186
2SA110	Ge-PNP	AM-Pre/Mix,20V,10mA,40MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1100	Si-PNP	GenP,LN,50V,0,2A,0,3W,200MHz	7b	Mit	BC214,BC416,BC560,2SA1136..1137,..
2SA1102	Si-PNP	AF,Sw-Pow,80V,6A,60W,20MHz	18j$	Sak	BD246B,BDV94,2SA1141,2SA1227(A)..
2SA1103	Si-PNP	AF,Sw-Pow,100V,7A,70W,20MHz	18j$	Sak	BD246C,BDV96,2SA1141,2SA1227(A)..
2SA1104	Si-PNP	AF,Sw-Pow,120V,8A,80W,20MHz	18j$	Sak	BD246C,2SA1141,2SA1186,2SA1227(A),..
2SA1105	Si-PNP	AF,Sw-Pow,120V,9A,90W,20MHz	18j$	Sak	BD246C,2SA1141,2SA1186,2SA1227(A),..
2SA1106	Si-PNP	AF,Sw-Pow,140V,10A,100W,20MHz	18j$	Sak	2SA1186,2SA1227A,2SA1386(A),2SB817,..
2SA1107(A)	Si-PNP	AF,Sw-Pow,150V,10A,120W,50MHz	20j$	Nec	2SA1076,2SA1095,2SA1166(A),2SA1389,..
2SA1108	Si-PNP	AF,Sw-Pow,130V,12A,120W,60MHz	20j$	Nec	2SA1076,2SA1095,2SA1166(A),2SA1389,..
2SA1108A	Si-PNP	=2SA1108:150V	20j$	-	2SA1076,2SA1095,2SA1166(A),2SA1389,..
2SA1109	Si-PNP	AF,Sw-Pow,180V,10A,200W,60MHz	23a$	Nec	MJ15016,2SA909,2SA1147,2SA1116..17..
2SA111	Ge-PNP	AM-Osc,20V,10mA,30MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1110	Si-PNP	AF,Sw-Pow,120V,0,5A,5W,200MHz	14h$	Mat.	2SA1178,2SA1184,2SA1220(A),2SA1358,MJE350...
2SA1111	Si-PNP	AF,Sw-Pow,150V,1A,20W,200MHz	17j$	Mat	2SA913(A),2SA968(A,B),2SA1011..
2SA1112	Si-PNP	=2SA1111:180V	17j$	Mat	2SA913A,2SA968A,B,2SA1011,2SA1133
2SA1113	Si-PNP	Dual,70V,0,2A,0,4W,100MHz	7-SIP/bp4	Mit	-
2SA1114	Si-PNP	GenP,LN,70V,0,2A,0,5W,150MHz	7b	Mit	2SA970,2SA1049,2SA1136..1137
2SA1115	Si-PNP	GenP,LN,50V,0,2A,0,3W,200MHz	41b	Mit	BC214,BC416,BC560,2SA1136..1137,..
2SA1116	Si-PNP	Sw,Pow,200V,15A,150W,20MHz	23a$	Sanken	MJ15016,2SA909,2SB552,2SB645
2SA1117	Si-PNP	Sw,Pow,200V,17A,200W,20MHz	23a$	Sanken	-
2SA112	Ge-PNP	AM-Mix,20V,10mA,20MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1120	Si-PNP	Lo-sat,35V,5A,10W,170MHz	14h$	Tos	2SA1357
2SA1121	Si-PNP	GenP,35V,0,5A,50MHz	35a	Hitachi	BC807,BCW67,BCX17,2SA1326..
2SA1121-B	Si-PNP	-	35	Hit	→2SA1121
2SA1121-C	Si-PNP	-	35	Hit	→2SA1121
2SA1121-D	Si-PNP	-	35	Hit	→2SA1121
2SA1122	Si-PNP	GenP,55V,0,1A	35a	Hitachi	BC856..857,BCW69..70,BCW89..
2SA1122-C	Si-PNP	-	35	Hit	→2SA1122
2SA1122-D	Si-PNP	-	35	Hit	→2SA1122
2SA1122-E	Si-PNP	-	35	Hit	→2SA1122
2SA1123	Si-PNP	GenP,LN,150V,0,05A,0,75W,200MHz	7c	Mat	2SA1016K,2SA1482
2SA1124	Si-PNP	=2SA1123:1W	7c(9mm)	Mat	2SA1482,(2SA1016K)
2SA1125	Si-PNP	=2SA1123:1,5W	17j$	Mat	-
2SA1126	Si-PNP	Sw,650V,0,1A,0,75W,15MHz	2a$	Hit	2SA911
2SA1127	Si-PNP	GenP,LN,60V,0,1A,0,4W,200MHz	7c	Mat	BC560,2SA1049,2SA1136..37,2SA1335,..
2SA1128	Si-PNP	GenP,25V,0,5A,0,6W,150MHz	7c	Mat	BC327..328,BC636,2SA1515,2SB910,..
2SA1129	Si-PNP	AF,Sw-Pow,30V,7A,40W,<1/3,5µS	17j$	Nec	BD244,BD544,BD796,BD806,2SB919..
2SA113	Ge-PNP	AM-Mix,34V,10mA,20MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1133(A)	Si-PNP	AF,Sw-Pow,TV-VD,200V,2A,30W,40MHz	17j$	Mat	BD240F,2SB720,2SB861
2SA1135	Si-PNP	AF,Sw-Pow,80V,4A,55W,10MHz	16j$	Sak	BD246B,BDV96,2SA1141,2SA1186..
2SA1136	Si-PNP	AF-Pre,LN,120V,0,1A,0,3W,90MHz	7c	Rhm	2SA941,2SA970,2SA992,2SA1049..
2SA1137	Si-PNP	=2SA1136:80V	7c	-	2SA941..942,2SA970,2SA992,2SA1049..
2SA1138(1)	Si-PNP	GenP,LN,80V,0,01A,0,6W,180MHz	9b	NEC	2SA941..942,2SA970,2SA992,2SA1049..
2SA114	Ge-PNP	AM-IF,34V,10mA,20MHz	4g	Fui	AF124..127,AF200,2SA218..227
2SA1141	Si-PNP	AF/HF-Pow,115V,10A,100W,90MHz	16j$	Nec	2SA1146,2SA1186
2SA1142	Si-PNP	AF-Dr-Pow,180V,0,1A,8W,180MHz	14h$	Nec	BF416,BF418,BF470,BF472,2SA1352
2SA1143	Si-PNP	GenP,20V,0,05A,0,2W,100MHz	7b	Mit	BC213,BC258,BC308,BC558..
2SA1144	Si-PNP	AF-Pow,150V,0,05A,10W,200MHz	14h$	Tos	BF416,BF418,BF470,BF472,2SA1352
2SA1145	Si-PNP	=2SA1144:0,8W	7c(9mm)	Tos	2SA1124,2SA1281,2SA1285A,2SA1482..
2SA1146	Si-PNP	AF/HF/Sw-Pow,140V,10A,100W,70MHz	18j$	Tos	2SA1186
2SA1147	Si-PNP	AF,Sw-Pow,180V,15A,150W,60MHz	23a$	Tos	MJ15016,2SA909,2SA1116..17,2SB645,..
2SA115	Ge-PNP	AM-Amp,34V,10mA,30MHz	4g	Fui	AF124..126,AF200,2SA218..227
2SA1150	Si-PNP	GenP,35V,0,8A,0,3W,120MHz	41c	Tos	BC327..328,BC636,BC638,BC640..
2SA1151	Si-PNP	GenP,60V,0,1A,0,25W,180MHz	7c	Nec	BC212,BC256,BC266,BC556..
2SA1152	Si-PNP	HF/Sw,80V,0,3A,0,6W,50/450nS	7c	Nec	BC640,2N4027,2N4029,2N5400..01..
2SA1153	Si-PNP	HF/Sw,60V,0,5A,0,6W,<35/255nS	7e	Nec	BSW24,2N2906..07(A),2N4026..29
2SA1154	Si-PNP	GenP,60V,0,7A,1W,120MHz	9b	NEC	BC638,BC640,2N2906..2907(A)..
2SA1155	Si-PNP	Dual,100V,0,1A,0,4W,100MHz	7-SIP/bp4	Mit	-
2SA1156	Si-PNP	Sw,Pow,400/400V,0,5A,10W,<1/5µS	14h$	Nec	2SA1775,(2SA1400)
2SA1158	Si-PNP	GenP,80V,0,1A,0,4W,>80MHz	7c	Tos	BC556,2SA970,2SA1049,2SA1285..

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2SA116	Ge-PNP	AM/FM-Pre., 30V, 10mA, 120MHz	4g	Fui	AF124..125, AF200, 2SA340..342
2SA1160	Si-PNP	Lo-sat, 20V, 2A, 0,9W, 140MHz	7c(9mm)	Tos	2SA1382, 2SB927, 2SB892, 2SB985
2SA1161	Si-PNP	UHF, 15V, 0,03A, 0,2W, 3,5GHz	7f	Tos	BFQ32, 2SA1057, 2SA1223, 2SA1228..
2SA1162	Si-PNP	GenP, 50V, 0,15A, >80MHz	35a	Toshiba	BC856..857, BCW69..70, BCW89, 2SA1311
2SA1162-GR	Si-PNP	-	35	Sanyo	→2SA1162
2SA1162-O	Si-PNP	-	35	Tos	→2SA1162
2SA1162-Y	Si-PNP	-	35	Tos	→2SA1162
2SA1163	Si-PNP	GenP, 120V, 0,1A, 100MHz	35a	Tos	2SA1312, 2SA1566
2SA1163-BL	Si-PNP	-	35	Tos	→2SA1163
2SA1163-GR	Si-PNP	-	35	Tos	→2SA1163
2SA1164	Si-PNP	HF/Sw, 35V, 0,1A, 0,2W, 30/320nS	7c	Tos	2N3250..51(A), 2N3905..06, 2N4034..35,..
2SA1166	Si-PNP	AF, Sw-Pow, 160V, 15A, 150W, 60MHz	20j$	Nec	2SA1076, 2SA1095, 2SA1215, 2SA1389..
2SA1166A	Si-PNP	=2SA1166: 180V	20j$	-	2SA1169..1170, 2SA1216, 2SA1333..
2SA1169	Si-PNP	AF, Sw-Pow, 200V, 15A, 150W, 20MHz	20j$	Sak	2SA1295, 2SA1333, 2SB756
2SA117	Ge-PNP	AM/FM-Osc, 30V, 10mA, 110MHz	4g	Fui	AF124..125, AF200, 2SA340..342
2SA1170	Si-PNP	AF, Sw-Pow, 200V, 17A, 200W, 20MHz	20j$	Sak	2SA1295
2SA1171	Si-PNP	AF/HF, 90V, 0,05A, 200MHz	35a	Hitachi	2SA1312, 2SA1466
2SA1171-D	Si-PNP	-	35	Hit	→2SA1171
2SA1171-E	Si-PNP	-	35	Hit	→2SA1171
2SA1173	Si-PNP	AF-Pre, 140V, 0,05A, 80MHz	39b	Nec	2SA1200, 2SB807, 2SB1046..1047
2SA1173-PK	Si-PNP	-	39	Nec	→2SA1173
2SA1173-PL	Si-PNP	-	39	Nec	→2SA1173
2SA1173-PM	Si-PNP	-	39	Nec	→2SA1173
2SA1174	Si-PNP	GenP, LN, 120V, 0,05A, 0,3W, 100MHz	40c	Nec	2SA1016(K), 2SA1038, 2SA1123..24..
2SA1175	Si-PNP	GenP, 60V, 0,1A, 0,25W, 180MHz	40c	Nec	BC212, BC256, BC266, BC556..
2SA1177	Si-PNP	FM, 30V, 30mA, 230MHz	40c	Sanyo	BF324, BF440..441, BF450..451..
2SA1178	Si-PNP	AF/HF-Pow, 150V, 1A, 20W, 200MHz	14h$	Mat	2SA1220A, 2SB649, 2SB1086A
2SA1179	Si-PNP	GenP, 55V, 0,15A, 180MHz	35a	Sanyo	BC856..857, BCW69..70, BCW89, 2SA1312
2SA1179-M4	Si-PNP	-	35	Sanyo	→2SA1179
2SA1179-M5	Si-PNP	-	35	Sanyo	→2SA1179
2SA1179-M6	Si-PNP	-	35	Sanyo	→2SA1179
2SA1179-M7	Si-PNP	-	35	Sanyo	→2SA1179
2SA118	Ge-PNP	AM/FM-Mix, 30V, 10mA, 100MHz	4g	Fui	AF124..125, AF200, 2SA340..342
2SA1180	Si-PNP	Sw, Pow, 180V, 10A, 100W	23a$	Fujitsu	MJ15016, BUW96, 2SA909, 2SA1116..17,..
2SA1180A	Si-PNP	=2SA1180: 200V	23a$	-	MJ15016, BUW96, 2SA909, 2SA1116..17,..
2SA1182	Si-PNP	GenP, 35V, 0,5A, 200MHz	35a	Toshiba	BC807, BCW68, BCX17, 2SA1313..
2SA1182-O	Si-PNP	-	35	Tos	→2SA1182
2SA1182-Y	Si-PNP	-	35	Tos	→2SA1182
2SA1183	Si-PNP-Darl	AF, Sw-Pow, 120V, 7A, 70W, B=15000	16j$	Tos	BDV64C
2SA1184	Si-PNP	AF-Dr-Pow, 120V, 1A, 15W, 120MHz	14h$	Tos	2SA1178, 2SA1220(A), 2SA1358, 2SB1086,..
2SA1185	Si-PNP	AF, Sw-Pow, 50V, 7A, 60W, 100MHz	18j$	Mat	2SA1141, 2SA1146, 2SA1186
2SA1186	Si-PNP	AF, Sw-Pow, 150V, 10A, 100W, 60MHz	18j$	Sak	2SA1227A, 2SA1386(A)
2SA1187	Si-PNP	=2SA1186: 12A, 120W	20j$	Sak	2SA1076, 2SA1095, 2SA1215, 2SA1166(A),..
2SA1188	Si-PNP	GenP, 90V, 0,1A, 0,4W, 130MHz	7c	Hit	2SA970, 2SA1049, 2SA1136, 2SA1285(A),..
2SA1189	Si-PNP	=2SA1188: 120V	7c	Hit	2SA970, 2SA1049, 2SA1136, 2SA1285(A),..
2SA119	Si-PNP	HF-Dr, 40V, 0,3A, 0,65W, 200MHz	2a$	Fui	BC303..304, BSW23, 2N2904..2905(A)..
2SA1190	Si-PNP	=2SA1188: ra	7c	Hit	2SA872, 2SA970, 2SA1049, 2SA1136,..
2SA1191	Si-PNP	=2SA1188: ra, 120V	7c	Hit	2SA872A, 2SA970, 2SA1049, 2SA1136,..
2SA1193(K)	Si-PNP-Darl	GenP, 60V, 0,5A, 0,9W, B>2000	7c(9mm)	Hit	BC876, BC878, BC880, BSR60..62, 2SB1405+
2SA1194(K)	Si-PNP-Darl	GenP, Pow, 60V, 1A, 8W, B>1000	14h$	Hit	BD678, BD778, BD876, BDX45..47..
2SA1195	Si-PNP	TV-AF-Pow, 160V, 1,5A, 15W, 50MHz	13j$	Toshiba	(2SA968(A,B), 2SA1011, 2SA1332,..)
2SA1196	Si-PNP	Sw, Pow, 400V, 0,1A, 10W	30j$	Hit	2SA1700, (BF891, 2SA1354, 2SB1011)
2SA1197	Si-PNP-Darl	=2SA1194:	30j$	Hit	2SB963..964
2SA1198(S)	Si-PNP	GenP, 80V, 0,05A, 0,4W, 140MHz	7c, 41c	Rhm	BC556, 2SA872(A), 2SA970, 2SA1285..
2SA1199(S)	Si-PNP	GenP, 50V, 0,7A, 0,4W, 100MHz	7c, 41c	Rhm	BC327, BC638, 2SB647, 2SB910, 2SB1116,..
2SA12	Ge-PNP	AM-IF, 16V, Ueb=0,5V, 15mA, 8MHz	2a	Hit	AF124..127, AF200, 2SA201..202
2SA120	Si-PNP	HF-Dr, 25V, 0,3A, 0,65W, 200MHz	2a$	Fui	BC303..304, BSW23, 2N2904..2905(A)..
2SA1200	Si-PNP	GenP, 150V, 0,05A, 120MHz	39b	Tos	2SB807, 2SB1046..1047
2SA1200-O	Si-PNP	-	39	Tos	→2SA1200
2SA1200-Y	Si-PNP	-	39	Tos	→2SA1200
2SA1201	Si-PNP	GenP, 120V, 0,8A, 120MHz	39b	Tos	2SB806, 2SB1025
2SA1201-O	Si-PNP	-	39	Tos	→2SA1201
2SA1201-Y	Si-PNP	-	39	Tos	→2SA1201
2SA1202	Si-PNP	GenP, 80V, 0,4A, 120MHz	39b	Tos	2SA1368, 2SB767, 2SB789(A)

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2SA1202-O	Si-PNP	-	39	Tos	→2SA1202
2SA1202-Y	Si-PNP	-	39	Tos	→2SA1202
2SA1203	Si-PNP	GenP,30V,1,5A,120MHz	39b	Tos	2SA1213,2SA1663,2SB1123,2SB1313,..
2SA1203-O	Si-PNP	-	39	Tos	→2SA1203
2SA1203-Y	Si-PNP	-	39	Tos	→2SA1203
2SA1204	Si-PNP	GenP,35V,0,8A,120MHz	39b	Tos	BCX51..53,2SA1364,2SB1734,2SB804,..
2SA1204-O	Si-PNP	-	39	Tos	→2SA1204
2SA1204-Y	Si-PNP	-	39	Tos	→2SA1204
2SA1205	Si-PNP	AF,Sw-Pow,70V,12A,100W,20MHz	18j$	Sak	BD246A,BD746A,BDV94,2SA1292..
2SA1206	Si-PNP	Sw,15V,0,05A,0,6W,<20/40nS	7e	Nec	BSX36,2N4313,2N5056..57
2SA1207	Si-PNP	GenP,180V,0,07A,0,6W,150MHz	7c	Sanyo	BF436..437,BF423A,2SA1281..
2SA1208	Si-PNP	GenP,180V,0,07A,0,9W,150MHz	7c(9mm)	Sanyo	BF436,BF423A,2SA1281,2SA1370..71
2SA1209	Si-PNP	GenP,Pow,180V,0,14A,10W,150MHz	14h$	Sanyo	BF416,BF418,2SA1352,2SA1407
2SA120A	Si-PNP	=2SA120:40V	2a$	-	BC303..304,BSW23,2N2904..2905(A)..
2SA121	Ge-PNP	FM,15V,2mA,100MHz	?2a	Son	AF124..125,AF106,AF306,2SA340..342
2SA1210	Si-PNP	GenP,Pow,200V,0,14A,10W	14h$	Sanyo	BF416,BF418,2SA1352,2SA1407..
2SA1211	Si-PNP	Sw,35V,0,1A,0,2W,400MHz	41c	Tos	BC213,BC308,BC558,2N2906..07..
2SA1214	Si-PNP	AF/HF/Sw-Pow,60V,2A,25W,35MHz	14h$	Tos	BD178,BD236,BD440,2SB1217,..
2SA1217	Si-PNP	AF-Pow,40V,3A,10W,100MHz	14h$	Tos	BD786,2SB744(A),2SB986..
2SA1218	Si-PNP	Sw,60V,0,6A,0,36W,<45/300nS	2a$	Nec	BSW24,2N2906..07(A),2N4026..29
2SA1219	Si-PNP	GenP,60V,0,1A,0,25W,180MHz	40c	Nec	BC212,BC256,BC266,BC556..
2SA122	Ge-PNP	FM,15V,2mA,100MHz	?2a	Son	AF124..125,AF106,AF306,2SA340..342
2SA1220	Si-PNP	AF/HF-Pow,120V,1,2A,20W,175MHz	14h$	Nec	2SA1249,2SB649
2SA1220A	Si-PNP	=2SA1220:160V	14h$	-	2SA1249,2SB649
2SA1221	Si-PNP	GenP,160/140V,0,5A,1W,45MHz	9b	NEC	2N5401,2SA1013,2SA1319
2SA1222	Si-PNP	GenP,160/160V,0,5A,1W,45MHz	9b	NEC	2N5401,2SA1013,2SA1319
2SA1223	Si-PNP	UHF,20V,0,05A,4GHz	25s	Nec	BFQ32,BFQ79,2SA801,2SA1057
2SA1224	Si-PNP	Sw,UHF,40V,0,2SA,2,5GHz	2g	Nec	-
2SA1225	Si-PNP	AF,Sw-Pow,160V,1,5A,15W,100MHz	30j$	Tos	2SA1552,2SB840..842,2SB1275
2SA1226	Si-PNP	HF,40V,30mA,400MHz	35a	Nec	BF536,BF550,BF568..569,BF660
2SA1226-2	Si-PNP	-	35	Sanyo	→2SA1226
2SA1226-3	Si-PNP	-	35	Sanyo	→2SA1226
2SA1226-4	Si-PNP	-	35	Sanyo	→2SA1226
2SA1227	Si-PNP	AF-Pow,140/140V,12A,120W,60MHz	16j$	Nec	2SA1386(A),2SB817
2SA1227A	Si-PNP	=2SA1227:160/160V	16j$	-	2SA1386(A),2SB817
2SA1228	Si-PNP	UHF,20V,0,05A,4GHz	5g	Nec	BFQ24
2SA1229	Si-PNP	Dual,UHF,20V,0,05A,4GHz	-	Nec	2SA1231
2SA123	Ge-PNP	FM,15V,2mA,100MHz	?2a	Son	AF124..125,AF106,AF306,2SA340..342
2SA1230	Si-PNP	UHF,15V,0,05A,8GHz	52s	Nec	-
2SA1231	Si-PNP	Dual,UHF,15V,0,05A,8GHz	-	Nec	-
2SA1232	Si-PNP	AF,Sw-Pow,130V,10A,100W,60MHz	16j$	Nec	2SA1146,2SA1186,2SA1227(A),2SA1386(A)
2SA1233	Si-PNP	Sw,Pow,400V,0,1A,10W	30j$	Hit	2SA1700,(2SA1354,2SB1011)
2SA1234	Si-PNP	UHF,20V,0,05A	52s	Nec	-
2SA1235	Si-PNP	GenP,50V,0,2A,200MHz	35a	Mitsubishi	BC856..857,BCW69..70,BCW89
2SA1235A	Si-PNP	=2SA1235:60V	35a	-	BC856,BCW89,2SA1620
2SA1235-E	Si-PNP	-	35	Mit	→2SA1235
2SA1235-F	Si-PNP	-	35	Mit	→2SA1235
2SA1235-G	Si-PNP	-	35	Mit	→2SA1235
2SA1236	Si-PNP	Sw,Pow,400V,2A,15W	17j$	Fui	2SA1009A,2SA1397
2SA1237	Si-PNP	Dual,55V,0,15A,0,5W,100MHz	-	Sanyo	-
2SA1238	Si-PNP	Dual,55V,0,15A,0,5W,100MHz	-	Sanyo	-
2SA1239	Si-PNP	Dual,130V,0,05A,0,5W,110MHz	-	Sanyo	-
2SA124	Ge-PNP	FM,15V,2mA,120MHz	?2a	Son	AF124..125,AF106,AF306,2SA340..342
2SA1240	Si-PNP	Dual,130V,0,05A,0,5W,160MHz	-	Sanyo	-
2SA1241	Si-PNP	AF,Sw-Pow,Lo-sat,50V,2A,10W,100MHz	30j$	Tos	2SB1201..02,2SB1215..16
2SA1242	Si-PNP	Sw,Pow,35V,5A,10W,170MHz	30j$	Tos	2SA1244,2SA1401,2SB1203..1204
2SA1243	Si-PNP	AF,Sw-Pow,30V,3A,15W,100MHz	30j$	Tos	2SB906,2SB962,2SB1184,2SB1202..03,..
2SA1244	Si-PNP	AF,Sw-Pow,Lo-sat,60V,5A,20W,60MHz	30j$	Tos	2SA1385,2SA1795,2SB1203..04
2SA1245	Si-PNP	UHF,15V,0,03A,4GHz	35a	Tos	BFT92..93
2SA1246	Si-PNP	Hi-Ueb,60V,0,15A,0,4W,100MHz	7c	Sanyo	2SA1253,(BC212,BC256,BC266,BC556)
2SA1247	Si-PNP	GenP,120V,0,05A,100MHz	35a	Nec	2SA1312,2SA1566
2SA1247-C25	Si-PNP	-	35	Nec	→2SA1247
2SA1247-C26	Si-PNP	-	35	Nec	→2SA1247
2SA1247-C27	Si-PNP	-	35	Nec	→2SA1247

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2SA1247-C28	Si-PNP	-	35	Nec	→2SA1247
2SA1248	Si-PNP	TV-AF-Pow,180/160V,0,7A,10W,120MHz	14h$	Sanyo	2SA1249,2SB649
2SA1249	Si-PNP	TV-AF-Pow,180/160V,1,5A,10W,120MHz	14h$	Sanyo	2SB649
2SA125	Ge-PNP	FM,15V,2mA,120MHz	?2a	Son	AF124..125,AF106,AF306,2SA340..342
2SA1250	Si-PNP	Sw,Pow,200V,8A,30W	22a$	Fui	-
2SA1251	Si-PNP	Sw,400V,0,15A,0,35W,<300/2300nS	2a$	Fui	2SA1625,2SB1074,2SB1488
2SA1252	Si-PNP	Hi-Ueb,60V,0,15A,100MHz	35a	Sanyo	2SA1434,(BC856,BCW89,2SA1312)
2SA1252-4	Si-PNP	-	35	Sanyo	→2SA1252
2SA1252-5	Si-PNP	-	35	Sanyo	→2SA1252
2SA1252-6	Si-PNP	-	35	Sanyo	→2SA1252
2SA1252-7	Si-PNP	-	35	Sanyo	→2SA1252
2SA1253	Si-PNP	Hi-Ueb,60V,0,2A,0,25W,100MHz	40c	Sanyo	2SA1246,(BC212,BC256,BC266,BC556)
2SA1254	Si-PNP	GenP,30V,0,03A,0,4W,300MHz	9c	Mat	BC308,BC558,BF324,BF414,BF939,+
2SA1255	Si-PNP	GenP,200V,0,05A,100MHz	35a	Tos	BF821,BF823,BFN23,2SA1330
2SA1256	Si-PNP	FM,30V,30mA,230MHz	35a	Sanyo	BF536,BF550,BF568,BF660
2SA1256-3	Si-PNP	-	35	Sanyo	→2SA1256
2SA1256-4	Si-PNP	-	35	Sanyo	→2SA1256
2SA1256-5	Si-PNP	-	35	Sanyo	→2SA1256
2SA1257	Si-PNP	Sw,AF-Dr,180V,0,08A,130MHz	35a	Sanyo	BFN25,BFN27,2SA1330
2SA1257-3	Si-PNP	-	35	Sanyo	→2SA1257
2SA1257-4	Si-PNP	-	35	Sanyo	→2SA1257
2SA1257-5	Si-PNP	-	35	Sanyo	→2SA1257
2SA1258	Si-P-Darl+Di	AF,Sw-Pow,70V,3A,20W,200MHz,B=5000	17j$	Sanyo	(BDT60A..C,BDW64B..D,2SB751A..B)
2SA1259	Si-P-Darl+Di	AF,Sw-Pow,70V,5A,30W,200MHz,B=5000	17j$	Sanyo	(BDW24B..C,BDW64B..D,2SB1339)
2SA126	Ge-PNP	Sw,12V,0,05A,50/110nS	2a	Nec	ASZ21,2N2955..2957
2SA1260	Si-P-Darl+Di	AF,Sw-Pow,70V,7A,40W,B=5000	17j$	Sanyo	BDT62A..C,BDX34B..D
2SA1261	Si-PNP	Sw,Pow,100V,10A,60W,<0,5/2µS	15j$	Nec	BD712,BD744C,BD912
2SA1262	Si-PNP	AF,Sw-Pow,Lo-sat,60V,4A,30W,15MHz	17j$	Sak	2SB920L,(BD536,BD540A,BD950,..)
2SA1263	Si-PNP	AF-Out,80V,6A,60W,30MHz	18j$	Tos	BD246B,BDV94,2SA1146,2SA1186..
2SA1264	Si-PNP	=2SA1263:120V,8A,80W	18j$	Tos	BD246C,2SA1141,2SA1186,2SA1227(A),..
2SA1264N	Si-PNP	120V,8A,80W,30MHz	-		-
2SA1265	Si-PNP	=2SA1263:140V,10A,100W	18j$	Tos	BD246D,2SA1146,2SA1186,2SA1227(A),..
2SA1265N	Si-PNP	140V,10A,100W,30MHz	-		-
2SA1266	Si-PNP	GenP,LN,50V,0,15A,0,4W,130MHz	7c	Kec	BC416,BC560,2SA970,2SA1136..1137,..
2SA1267	Si-PNP	=2SA1266:0,2W	41c	Kec	BC416,BC560,2SA970,2SA1136..1137,..
2SA1268	Si-PNP	GenP,LN,120V,0,1A,0,3W,100MHz	7c	Kec	2SA970,2SA1049,2SA1038,2SA1136..
2SA1269	Si-PNP	=2SA1268:0,2W	41c	Kec	2SA970,2SA1049,2SA1038,2SA1136..
2SA127	Ge-PNP	HF,70V,50mA,25MHz	4g	Tos	AF118,SFT162,2SA358
2SA1270	Si-PNP	GenP,35V,0,5A,0,5W,200MHz	7c	Kec	BC327,BC636,2SA1515,2SB910,..
2SA1271	Si-PNP	GenP,35V,0,8A,0,6W,120MHz	7c	Kec	BC327,BC636,2SB909..910,2SB734,..
2SA1272	Si-PNP	=2SA1271:0,3W	41c	Kec	BC327,BC636,2SB909..910,2SB734,..
2SA1273	Si-PNP	AF-Dr/Out,30V,2A,1W,120MHz	7c(9mm)	Kec	2SB892,2SB927,2SB1312,2SA1382
2SA1274	Si-PNP	AF-Dr/Out,80V,0,4A,0,8W,100MHz	7c(9mm)	Kec	BC640,2N5400..5401,2SA965,2SA1533,..
2SA1275	Si-PNP	AF-Dr/Out,160V,1A,0,9W,50MHz	7c(9mm)	Kec	2SA1013,2SB1212
2SA1276	Si-PNP	AF,Sw-Pow,30V,3A,10W,100MHz	17j$	Kec	2SA473,2SA1012,2SA1288..1289
2SA1277	Si-PNP	AF,Sw-Pow,30V,3A,20W,100MHz	?15j$	Tos	2SA473,2SA1012,2SA1288..1289
2SA1278	Si-PNP	AF,Sw-Pow,160V,1,5A,25W,100MHz	?15j$	Tos	2SA968(A..B),2SA1011,2SA1079,2SA1332
2SA1279	Si-PNP	Lo-sat,60V,5A,25W,60MHz	?1Sj$	Tos	2SA1012,2SA1289..91,2SA1293
2SA128	Ge-PNP	Sw,40V,0,6A,0,17W,>15MHz,a>15	4g	Tos	ASY76..77
2SA1280	Si-PNP	TV-VD-Out,150V,1,5A,25W,4MHz	?1Sj$	Tos	2SB608,2SB628(A),2SB861,2SB991..
2SA1281	Si-PNP	GenP,180V,0,1A,0,9W,130MHz	7c(9mm)	Mit	BF436,BF423A,2SA1370
2SA1282	Si-PNP	20V,2A,0.9W,80MHz	-		-
2SA1282(A)	Si-PNP	GenP,20V,2A,0,9W,80MHz	7c(9mm)	Mit	2SA1382,2SB738..739,2SB892,2SB1312,..
2SA1283	Si-PNP	GenP,60V,1A,0,9W,85MHz	7c(9mm)	Mit	2SA1315,2SB647,2SB892,2SB1041,..
2SA1284	Si-PNP	GenP,100V,0,5A,0,9W,130MHz	7c(9mm)	Mit	BC640,2N5400..5401,2SA695,2SB1297,..
2SA1285	Si-PNP	GenP,120V,0,1A,0,9W,200MHz	7c(9mm)	Mit	2SA1281,2SA1124,2SA1482
2SA1285A	Si-PNP	=2SA1285:150V	7c(9mm)	-	2SA1124,2SA1281,2SA1482
2SA1286	Si-PNP	Hi-beta,Lo-sat,30V,1,5A,0,9W,B>400	7c(9mm)	Mit	(2SB892,2SB927)
2SA1287	Si-PNP	Lo-sat,50V,1A,0,9W,90MHz,B>400	7c(9mm)	Mit	(2SA1315,2SB892,2SB1229)
2SA1288	Si-PNP	AF,Sw-Pow,80V,3A,30W,100MHz	17j$	Sanyo	MJE15029,2SA1293
2SA1289	Si-PNP	AF,Sw-Pow,Lo-sat,80V,5A,30W,100MHz	17j$	Sanyo	2SA1293
2SA129	Ge-PNP	=2SA128:a>35	4g	Tos	ASY76..77
2SA1290	Si-PNP	AF,Sw-Pow,Lo-sat,80V,7A,35W,100MHz	17j$	Sanyo	2SA1329
2SA1291	Si-PNP	AF,Sw-Pow,Lo-sat,80V,10A,40W,100MHz	17j$	Sanyo	2SA1329

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2SA1292	Si-PNP	AF, Sw-Pow, Lo-sat, 80V, 15A, 70W, 100MHz	18j$	Sanyo	(2SB922L)
2SA1293	Si-PNP	Lo-sat, 100V, 5A, 30W, 60MHz	17j$	Tos	-
2SA1294	Si-PNP	AF, Sw-Pow, 230V, 15A, 130W, 35MHz	18j$	Sak	2SA1986
2SA1295	Si-PNP	AF, Sw-Pow, 230V, 17A, 200W, 35MHz	20j$	Sak	-
2SA1296	Si-PNP	GenP, 20V, 2A, 0,75W, 120MHz	7c	Tos	2SA1315, 2SA1382, 2SB985, 2SB911,..
2SA1297	Si-PNP	=2SA1296: 0,4W	41c	Tos	2SA1315, 2SA1382, 2SB985, 2SB911,..
2SA1298	Si-PNP	GenP, 30V, 0,8A, 120MHz	35a	Toshiba	BCW67..68, 2SA1621
2SA1298-O	Si-PNP	-	35	Tos	→2SA1298
2SA1298-Y	Si-PNP	-	35	Tos	→2SA1298
2SA1299	Si-PNP	GenP, LN, 50V, 0,2A, 0,3W, 200MHz	41c	Mit	BC416, BC560, 2SA970, 2SA1136..1137,..
2SA12H	Ge-PNP	=2SA12: Ueb=12V	2a	-	-
2SA13	Ge-PNP	AM-IF, 12V, 15mA, 8MHz	2a	Hit	AF124..127, AF200, 2SA201..202
2SA130	Ge-PNP	AM-Amp, 9V, 10mA, 65MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA1300	Si-PNP	GenP, Lo-sat, 20V, 2A, 0,75W, 140MHz	7c	Tos	2SB926..927, 2SB892, 2SB1229
2SA1301	Si-PNP	AF-Out, 160V, 12A, 120W, 30MHz	77j$	Tos	2SA1553, 2SB1153, 2SB1162..63, 2SB1347..
2SA1302	Si-PNP	AF-Pow, 200V, 15A, 150W, 30MHz	77j$	Tos	2SA1553
2SA1303	Si-PNP	AF, Sw-Pow, 150V, 14A, 125W, 50MHz	18j$	Sak	2SA1227A, 2SA1386(A), 2SB817
2SA1304	Si-PNP	TV-VD, AF, Sw, Pow, 150V, 1,5A, 20W, 4MHz	17c	Tos	2SA1306, 2SA1332, 2SA1606, 2SB1338,..
2SA1305	Si-PNP	AF, Sw-Pow, 30V, 3A, 15W, 100MHz	17c	Tos	2SA1307, 2SB1185, 2SB1274
2SA1306	Si-PNP	AF, Sw-Pow, 160V, 1,5A, 20W, 100MHz	17c	Tos	2SA1332, 2SA1606, 2SB1186A
2SA1306A	Si-PNP	=2SA1306: 180V	17c	-	2SA1606
2SA1306B	Si-PNP	=2SA1306: 200V	17c	-	-
2SA1307	Si-PNP	DC-DC-Conv., Lo-sat, 60V, 5A, 20W, 60MHz	17c	Tos	2SA1388, 2SA1469..70, 2SA1441, TIP42C
2SA1308	Si-PNP	Sw, Pow, Lo-sat, 100V, 5A, 30W, 60MHz	?15j$	Tos	2SA1293
2SA1309	Si-PNP	GenP, 30V, 0,1A, 0,3W, 80MHz	40c	Mat	BC213, BC258, BC308, BC558..
2SA1309A	Si-PNP	=2SA1309: 60V	40c	-	BC212, BC257, BC307, BC557..
2SA131	Ge-PNP	AM-Osc, 9V, 10mA, 45MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA1310	Si-PNP	GenP, LN, 60V, 0,1A, 0,3W, 200MHz	40c	Mat	BC416, BC560, 2SA970, 2SA1136..1137,..
2SA1311	Si-PNP	GenP, LN, 60V, 0,15A, 150MHz	35a	Toshiba	2SA1312
2SA1312	Si-PNP	GenP, LN, 120V, 0,1A, 100MHz	35a	Toshiba	2SB792
2SA1312-BL	Si-PNP	-	35	Tos	→2SA1312
2SA1312-GR	Si-PNP	-	35	Tos	→2SA1312
2SA1313	Si-PNP	GenP, 50V, 0,5A, 200MHz	35a	Toshiba	BC807, BCX17, 2SA1366
2SA1313-O	Si-PNP	-	35	Tos	→2SA1313
2SA1313-Y	Si-PNP	-	35	Tos	→2SA1313
2SA1314	Si-PNP	Lo-sat, 20V, 2A, 140MHz	39b	Tos	2SB1121..23
2SA1314-A	Si-PNP	-	39	Tos	→2SA1314
2SA1314-B	Si-PNP	-	39	Tos	→2SA1314
2SA1314-C	Si-PNP	-	39	Tos	→2SA1314
2SA1315	Si-PNP	GenP, Lo-sat, 80V, 2A, 0,9W, 80MHz	7c(9mm)	Tos	2SB1459
2SA1316	Si-PNP	GenP, LN, 80V, 0,1A, 0,4W, 50MHz	7c	Tos	2SA970, 2SA1038, 2SA1049, 2SA1136..37,..
2SA1317	Si-PNP	GenP, 60V, 0,2A, 0,3W, 200MHz	40c	Sanyo	BC212, BC256, BC266, BC556..
2SA1318	Si-PNP	=2SA1317: 0,5W	7c	Sanyo	BC212, BC256, BC266, BC556..
2SA1319	Si-PNP	GenP, 180V, 0,7A, 0,7W, 120MHz	7c	Sanyo	2SA1768
2SA132	Ge-PNP	AM-Mix, 9V, 10mA, 50MHz	4g	Hit	AF124..126, AF200, 2SA218..227
2SA1320	Si-PNP	Vid, 250V, 0,05A, 0,6W, 80MHz	7c	Tos	BF423, BF436..437, 2SA1371..1372..
2SA1321	Si-PNP	=2SA1320: 0,9W	7c(9mm)	Tos	BF423, BF436..437, 2SA1371..1372..
2SA1322	Si-PNP	=2SA1320: 5W	14h$	Tos	BF416, BF418, BF470, BF472..
2SA1323	Si-PNP	GenP, 30V, 0,03A, 0,3W, 300MHz	40c	Mat	BC308, BC558, BF324, BF414, BF939,+
2SA1324	Si-PNP	GenP, 50V, 0,15A, >80MHz	35d	Tos	BC856R..857R, BCW69..70R, BCW89R..
2SA1324-GR	Si-PNP	-	35	Tos	→2SA1324
2SA1324-O	Si-PNP	-	35	Tos	→2SA1324
2SA1324-Y	Si-PNP	-	35	Tos	→2SA1324
2SA1325	Si-PNP	GenP, 120V, 0,1A, 100MHz	35d	Tos	(2SA1312)
2SA1325-BL	Si-PNP	-	35	Tos	→2SA1325
2SA1325-GR	Si-PNP	-	35	Tos	→2SA1325
2SA1326	Si-PNP	GenP, 35V, 0,5A, 200MHz	35d	Tos	2N6490, BC807R, BCW68R, BCX17R
2SA1326-O	Si-PNP	-	35	Tos	→2SA1326
2SA1326-Y	Si-PNP	-	35	Tos	→2SA1326
2SA1327(A)	Si-PNP	Lo-sat, 50V, 10A, 20W, 50MHz	17c	Tos	2SA1471, 2SA1567..68
2SA1328	Si-PNP	DC-DC-Conv., Lo-sat, 60V, 12A, 40W, 70MHz	17j$	Tos	2SB903
2SA1329	Si-PNP	=2SA1328: 80V, 50MHz	17j$	Tos	2SA1329, BD912
2SA133	Ge-PNP	AM-Mix, 9V, 10mA, 40MHz	4g	Hit	AF124..127, AF200, 2SA218..227
2SA1330	SI-PNP	Sw, 200V, 0,1A, 120MHz, 150/1500nS	35a	NEC	BFN25, BFN27

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2SA1330-05	Si-PNP	-	35	Nec	→2SA1330
2SA1330-06	Si-PNP	-	35	Nec	→2SA1330
2SA1330-07	Si-PNP	-	35	Nec	→2SA1330
2SA1331	Si-PNP	Sw,60V,0,15A,100MHz,160/390nS	35a	Sanyo	BC856,BCW89,BSR15..16,2SA1338..
2SA1331-04	Si-PNP	-	35	Sanyo	→2SA1331
2SA1331-05	Si-PNP	-	35	Sanyo	→2SA1331
2SA1331-06	Si-PNP	-	35	Sanyo	→2SA1331
2SA1331-4	Si-PNP	-	35	Sanyo	→2SA1331
2SA1331-5	Si-PNP	-	35	Sanyo	→2SA1331
2SA1331-6	Si-PNP	-	35	Sanyo	→2SA1331
2SA1332	Si-PNP	AF,Sw-Pow,160V,1,5A,20W,200MHz	17c	Tos	2SA1306(A,B),2SA1606
2SA1333	Si-PNP	AF,Sw-Pow,200V,15A,150W,30MHz	20j$	Tos	2SA1169..1170,2SA1295,2SB756
2SA1334	Si-PNP	GenP,30V,0,8A,0,6W,120MHz	7c	Toshiba	BC327..328,BC636,2SB909..910..
2SA1335	Si-PNP	GenP,LN,120V,0,1A,0,2W,100MHz	41c	Tos	2SA970,2SA1038,2SA1049,2SA1136..37,..
2SA1336	Si-PNP	GenP,20V,2A,0,7W,80MHz	7c	Mit	MPS750,2SA1382,2SB738..739,2SB892,..
2SA1337	Si-PNP	GenP,55V,0,1A,0,3W,200MHz	41c	Hit	BC212,BC257,BC307,BC557..
2SA1338	Si-PNP	-	35	Sanyo	→2SA1338
2SA1339	Si-PNP	Sw,60V,0,5A,0,3W,200MHz,70/450nS	40c	Sanyo	BSW24,2N2906..07(A),2N4026..29..
2SA134	Ge-PNP	FM,20V,10mA,140MHz	1g	Hit	AF124..125,AF106,AF306,2SA213..216
2SA1340	Si-PNP	GenP,55V,0,1A,0,4W,200MHz	9c	Hit	BC212,BC257,BC307,BC557..
2SA1341	Si-PNP	-	35	Sanyo	→2SA1341
2SA1342	Si-PNP	-	35	Sanyo	→2SA1342
2SA1343	Si-PNP	-	35	Sanyo	→2SA1343
2SA1344	Si-PNP	-	35	Sanyo	→2SA1344
2SA1345	Si-PNP-Digital	R1=R2=47kΩ,50V,0,1A,200MHz	40c	Sanyo	AN1L4M,DTA144ES,RN2004,UN4113,..
2SA1346	Si-PNP-Digital	R1=R2=22kΩ,50V,0,1A,200MHz	40c	Sanyo	AN1F4M,DTA124ES,RN2003,UN4112,..
2SA1347	Si-PNP-Digital	R1=46kΩ,R2=23kΩ,50V,0,1A,200MHz	40c	Sanyo	AN1L4L,DTA144WS,RN2009,UN411E,..
2SA1348	Si-PNP-Digital	R1=R2=10kΩ,50V,0,1A,200MHz	40c	Sanyo	AN1A4M,DTA114ES,RN2002,UN4111,..
2SA1349	Si-PNP	Dual,80V,0,1A,0,4W,170MHz	7-SIP	Tos	-
2SA135	Ge-PNP	FM,20V,10mA,150MHz	1g	Hit	AF124..125,AF106,AF306,2SA213..216
2SA1350	Si-PNP	GenP,40V,0,1A,0,3W,200MHz	41c	Hit	BC212,BC257,BC307,BC557..
2SA1351	Si-PNP	=2SA1350:0,4W	9c	Hit	BC212,BC257,BC307,BC557..
2SA1352	Si-PNP	Vid,Hi-def,200V,0,1A,5W,70MHz	14h$	Sanyo	2SA1380..81,2SA1406..07
2SA1353	Si-PNP	=2SA1352:300V	14h$	Sanyo	2SA1381,(BF418)
2SA1354	Si-PNP	=2SA1352:400V	14h$	Sanyo	(2SB1011)
2SA1355	Si-PNP	AF,Sw-Pow,70V,4A,30W,40MHz	17j$	Sak	BD244A,BD538,BD540B,2SA1289..
2SA1356	Si-PNP	Lo-sat,40V,0,8A,5W,100MHz	14b	Tos	2SB1144,(BD136,BD227,BD376,..)
2SA1357	Si-PNP	Lo-sat,35V,5A,10W,170MHz	14b	Tos	TIP42C
2SA1358	Si-PNP	AF-Pow,120V,1A,10W,120MHz	14b	Tos	2SB1144,(2SA1178,2SA1184,2SA1220(A))
2SA1359	Si-PNP	AF,Sw-Pow,40V,3A,10W,100MHz	14b	Tos	2SB1143,(BD786,MJE250..252,2SA1217)
2SA136	Ge-PNP	AM-Pre/Mix/Osc,6V,10mA,10MHz	2a	Fui	AF124..126,AF200,2SA218..227
2SA1360	Si-PNP	AF-Pow,150V,0,05A,5W,200MHz	14b	Tos	2SA1477..78,2SA1540,(BF418,BF470..)
2SA1361	Si-PNP	Sw,Vid-Pow,250V,0,05A,80MHz	14b	Tos	2SA1479..80,(BF416,BF418,BF470,..)
2SA1362	Si-PNP	GenP,15V,0,8A,120MHz	35a	Tos	BCW67..68,2SA1298
2SA1362-BL	Si-PNP	-	35	Tos	→2SA1362
2SA1362-GR	Si-PNP	-	35	Tos	→2SA1362
2SA1362-Y	Si-PNP	-	35	Tos	→2SA1362
2SA1363	Si-PNP	Lo-sat,20V,2A,80MHz	39b	Mit	2SA1314,2SA1369,2SB1121
2SA1363-E	Si-PNP	-	39	Mit	→2SA1363
2SA1363-F	Si-PNP	-	39	Mit	→2SA1363
2SA1363-G	Si-PNP	-	39	Mit	→2SA1363
2SA1364	Si-PNP	Lo-sat,60V,1A,85MHz	39b	Mit	2SA1681,2SB1115,2SB1122..1123,..
2SA1364-C	Si-PNP	-	39	Mit	→2SA1364
2SA1364-D	Si-PNP	-	39	Mit	→2SA1364
2SA1364-E	Si-PNP	-	39	Mit	→2SA1364
2SA1365	Si-PNP	GenP,25V,0,7A,180MHz	35a	Mitsubishi	BCW67..68,2SA1298,2SA1621
2SA1365-E	Si-PNP	-	35	Mit	→2SA1365
2SA1365-F	Si-PNP	-	35	Mit	→2SA1365
2SA1365-G	Si-PNP	-	35	Mit	→2SA1365
2SA1366	Si-PNP	GenP,55V,0,4A,150MHz	35a	Mitsubishi	BCW68,BCX42,2SB1198
2SA1366-D	Si-PNP	-	35	Mit	→2SA1366
2SA1366-E	Si-PNP	-	35	Mit	→2SA1366
2SA1366-F	Si-PNP	-	35	Mit	→2SA1366
2SA1367	Si-PNP	GenP,50V,0,1A,0,3W,100MHz	41c	Mit	BC212,BC257,BC307,BC557..

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2SA1368	Si-PNP	GenP, 100V, 0,5A, 130MHz	39b	Mit	2SA1201, 2SB789(A), 2SB805..806
2SA1368-C	Si-PNP	-	39	Mit	→2SA1368
2SA1368-D	Si-PNP	-	39	Mit	→2SA1368
2SA1368-E	Si-PNP	-	39	Mit	→2SA1368
2SA1369	Si-PNP	Lo-sat, 30V, 1,5A, 90MHz, B>400	39b	Mit	(2SA1314, 2SB1121)
2SA1369-G	Si-PNP	-	39	Mit	→2SA1369
2SA1369-H	Si-PNP	-	39	Mit	→2SA1369
2SA137	Ge-PNP	AM-IF, 6V, 10mA, 5MHz	2a	Fui	, AF124..127, AF200, 2SA218..227
2SA1371E	Si-PNP	300V, 0.1A, 1W, 150MHz	-		-
2SA1372	Si-PNP	=2SA1370: 400V	7c(9mm)	-	(2SA1251, 2SA1584, 2SA1760)
2SA1373	Si-PNP	GenP, 60V, 0,2A, 0,4W, 250MHz	7b	Hit	BC212, BC256, BC266, BC556..
2SA1374	Si-PNP	GenP, 55V, 0,1A, 0,3W, 250MHz	40c	Hit	BC212, BC256, BC266, BC556..
2SA1375	Si-PNP	Sw, Vid-Pow, 250V, 0,07A, 10W, 80MHz	30j$	Mat	2SA1700, (BF416, BF616, BF848..849..)
2SA1376	Si-PNP	200V, 0.1A, 0.75W, 120MHz	-		-
2SA1376(A)	Si-PNP	Sw, Vid, 200V, 0,1A, 0,75W, 120MHz	7c	Nec	BF423, BF436..437, 2SA1370..1372
2SA1377	Si-PNP	GenP, 55V, 0,1A, 0,3W, 150MHz	7c	Tos	BC212, BC256, BC266, BC556..
2SA1378	Si-PNP	GenP, 35V, 0,5A, 0,3W, 200MHz	41c	Tos	BC327..328, BC636, 2SA1515, 2SB910,..
2SA1379	Si-PNP	Sw, Pow, 600V, 0,8A, 10W	30j$	Hit	2SA1413, 2SA1807
2SA138	Ge-PNP	Sw, 20V, Ueb=10V, 25mA, 0,08W, 15MHz	2a	Fui	ASY26..27, ASY48
2SA1380	Si-PNP	Vid-Pow, Hi-def, 200V, 0,1A, 7W, 150MHz	14h$	Sanyo	2SA1352..53, 2SA1406..07
2SA1381	Si-PNP	=2SA1380: 300V	14h$	Sanyo	2SA1353..54
2SA1382	Si-PNP	GenP, 50V, 2A, 0,9W, 110MHz	7c(9mm)	Tos	2SA1315, 2SB892, 2SB1312
2SA1383	Si-PNP	AF-Pow, 180V, 0,1A, 10W, 180MHz	17j$	Nec	2SA1476, (BF616, BF848..849, BF760..)
2SA1384	Si-PNP	Vid, 300V, 0,1A, 70MHz	39b	Tos	BFN19
2SA1384-O	Si-PNP	-	39	Tos	→2SA1384
2SA1384-R	Si-PNP	-	39	Tos	→2SA1384
2SA1385	Si-PNP	AF, Sw-Pow, 60V, 5A, 10W	30j$	Nec	2SA1244, 2SA1401, 2SB1203..04, (BD244A..)
2SA1386	Si-PNP	AF, Sw-Pow, 160V, 15A, 130W, 40MHz	18j$	Sak	2SA1294
2SA1386A	Si-PNP	=2SA1386: 180V	18j$	-	2SA1294
2SA1387	Si-PNP	Sw, Pow, Lo-sat, 60V, 5A, 20W, 80MHz	17c	Tos	2SA1307, 2SA1469, (2SA1293)
2SA1388	Si-PNP	AF, Sw-Pow, Lo-sat, 100V, 5A, 25W, 60MHz	17c	Tos	2SA1741..42, (2SA1293)
2SA1389	Si-PNP	AF, Sw-Pow, 160V, 12A, 120W, 30MHz	20j$	Tos	2SA1076, 2SA1095, 2SA1166(A), 2SA1215,..
2SA139	Ge-PNP	Sw, 20V, Ueb=10V, 50mA, 0,08W, 8MHz	2a	Fui	ASY26..27, ASY48
2SA1390	Si-PNP	GenP, 35V, 0,5A, 0,3W, 120MHz	40c	Hit	BC327..328, BC636, 2SA1515, 2SB910,..
2SA1391	Si-PNP	=2SA1392: ra	7c	Sanyo	BC416, BCS60, 2SA970, 2SA1136..1137,..
2SA1392	Si-PNP	AF, 60V, 0,2A, 0,4W, 200MHz	7c	Sanyo	BC212, BC256, BC266, BC556..
2SA1393	Si-PNP	AF, Sw-Pow, 120V, 1,5A, 20W, 180MHz	17c	Nec	2SA1306(A,B), 2SA1332, 2SA1606
2SA1394	Si-PNP	AF, Sw-Pow, Hi-Ueb, 80V, 5A, 25W	17c	Nec	(2SA1469, 2SB1016, 2SB1294)
2SA1395	Si-PNP	AF, Sw-Pow, 100V, 2A, 15W	17c	Nec	2SA1440, 2SB1095, 2SB1338
2SA1396	Si-PNP	AF, Sw-Pow, 100V, 10A, 30W	17c	Nec	2SA1443, 2SA1652, (BD712, BD744C,..)
2SA1397	Si-PNP	Sw, Pow, 400V, 2A, 15W	17c	Nec	2SA1501, (2SA1009A, 2SA1236)
2SA1398	Si-PNP	GenP, 25V, 0,7A, 0,9W, 180MHz	7c(9mm)	Mit	2SA966, 2SA1382, 2SB978, 2SB1041
2SA1399	Si-PNP	GenP, 55V, 0,4A, 0,9W, 150MHz	7c(9mm)	Mit	BC638, 2N5400..01, 2SA965, 2SA1533..
2SA14	Ge-PNP	HF/AF, 16V, 15mA, 4MHz	2a	Hit	AF124..127, AF200, 2SA201..203
2SA1400	Si-PNP	Sw, Pow, 400V, 0,5A, 10W, <1/6µS	30j$	Nec	2SA1379, 2SA1413
2SA1401	Si-PNP	AF, Sw-Pow, 60V, 5A, 10W	30j$	Nec	2SA1385, 2SB1203..04, 2SB1244, (BD244A..)
2SA1402	Si-PNP	Vid-Out, Hi-def, 80V, 0,3A, 8W, 700MHz	14h$	Sanyo	2SA1405
2SA1403	Si-PNP	Vid-Out, Hi-def, 80V, 0,5A, 10W, 800MHz	14h$	Sanyo	-
2SA1404	Si-PNP	Vid-Out, Hi-def, 120V, 0,2A, 8W, 500MHz	14h$	Sanyo	2SA1405
2SA1405	Si-PNP	Vid-Out, Hi-def, 120V, 0,3A, 8W, 500MHz	14h$	Sanyo	-
2SA1406	Si-PNP	Vid-Out, Hi-def, 200V, 0,1A, 7W, 400MHz	14h$	Sanyo	2SA1352, 2SA1407
2SA1407	Si-PNP	Vid-Out, Hi-def, 200V, 0,15A, 7W, 400MHz	14h$	Sanyo	-
2SA1408	Si-PNP	CTV-VD, AF-Pow, 150V, 1,5A, 10W, 50MHz	14b	Tos	2SA1507, (2SA1249, 2SB649)
2SA1409	Si-PNP	Hi-beta, Sw, 25V, 0,15A, 0,25W, B=1000	7c	Nec	2SA1436, (BC213, BC308, BC558,..)
2SA141	Ge-PNP	AM-IF, 15V, 15mA, 4MHz	2a	Mit	AF124..127, AF200, 2SA201..203
2SA1410	Si-PNP	=2SA1409:	40c	Nec	2SA1436, (BC213, BC308, BC558,..)
2SA1411	Si-PNP	=2SA1409: SMD	35a	Nec	(BC856..858, BCW29..30, BCW69..70,..)
2SA1411-M15	Si-PNP	-	35	Nec	→2SA1411
2SA1411-M16	Si-PNP	-	35	Nec	→2SA1411
2SA1412	Si-PNP	Sw, Pow, 400/400V, 2A, 10W, 40MHz	30j$	Nec	2SA1773
2SA1413	Si-PNP	Sw, Pow, 600/600V, 1A, 10W, 28MHz	30j$	Nec	2SA1379, 2SA1807
2SA1415	Si-PNP	GenP, 180V, 0,14A, 150MHz	39b	Sanyo	BFN17, BFN19
2SA1416	Si-PNP	GenP, 120V, 1A, 120MHz	39b	Sanyo	2SA1419, 2SB1025..1028
2SA1417	Si-PNP	GenP, 120V, 2A, 120MHz	39b	Sanyo	2SA1419, 2SB1027..28

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2SA1418	Si-PNP	GenP, 180V, 0,7A, 120MHz	39b	Sanyo	2SA1419, 2SB1027..1028
2SA1419	Si-PNP	GenP, 180V, 1,5A, 120MHz	39b	Sanyo	2SB1027..28
2SA142	Ge-PNP	AM-Pre/Mix, 15V, 15mA, 8MHz	2a	Mit	AF124..126, AF200, 2SA201..203
2SA1420	Si-PNP-Digital	=2SA1345: 0,4W	7c	Sanyo	→2SA1345
2SA1421	Si-PNP-Digital	=2SA1346: 0,4W	7c	Sanyo	→2SA1346
2SA1422	Si-PNP-Digital	=2SA1347: 0,4W	7c	Sanyo	→2SA1347
2SA1423	Si-PNP-Digital	=2SA1348: 0,4W	7c	Sanyo	→2SA1348
2SA1424	Si-PNP	UHF, 20V, 0,05A, 4GHz	35a	Nec	BFT93
2SA1425	Si-PNP	GenP, 120V, 0,8A, 1W, 120MHz	9c	Tos	2SA965, 2SA1013, 2SA1319, 2SA1768,..
2SA1426	Si-PNP	GenP, 35V, 0,8A, 1W, 120MHz	9c	Tos	BC327, BC636, 2SB909..910,..
2SA1427	Si-PNP	GenP, 30V, 1,5A, 1W, 120MHz	9c	Tos	MPS750, 2SA966, 2SB819, 2SB892, 2SB978..
2SA1428	Si-PNP	GenP, 50V, 2A, 1W, 100MHz	9c	Tos	MPS750..751, 2SB892, 2SB1433..34,..
2SA1429	Si-PNP	GenP, 80V, 2A, 1W, 80MHz	9c	Tos	MPS751, 2SA1315, 2SB1459
2SA142A	Ge-PNP	=2SA142: 40V	2a	-	2SA102..104
2SA143	Ge-PNP	AM-Pre/Mix, 15V, 15mA, 15MHz	2a	Mit	AF124..126, AF200, 2SA202
2SA1430	Si-PNP	GenP, Lo-sat, 20V, 2A, 1W, 140MHz	9c	Tos	MPS750, 2SB733, 2SB738..739, 2SB892..
2SA1431	Si-PNP	GenP, 35V, 5A, 1W, 170MHz	9c	os	2SB1446
2SA1432	Si-PNP	Vid, 300V, 0,1A, 1W, 60MHz	9c	Tos	BF421A, BF437, BF493, 2SA1624,..
2SA1433	Si-PNP	Vid, Hi-def, 70V, 0,05A, 0,9W, 700MHz	7c(9mm)	Sanyo	-
2SA1434	Si-PNP	Hi-beta, Hi-Ueb, 60V, 0,1A, B>500	35a	Sanyo	-
2SA1435	Si-PNP	Hi-beta, Hi-Ueb, Lo-sat, 30V, 0,3A, B>500	7c	Sanyo	-
2SA1436	Si-PNP	Hi-beta, Hi-Ueb, Lo-sat, 60V, 0,2A, B>500	7c	Sanyo	-
2SA1437	Si-PNP	Hi-beta, Hi-Ueb, 120V, 0,05A, 85MHz, B>400	7c	Sanyo	-
2SA1438	Si-PNP	Hi-beta, Hi-Ueb, 30V, 1,2A, B>500	7c(9mm)	Sanyo	-
2SA144	Ge-PNP	AM-Pre/Mix/Osc/IF, 15V, Ueb=10V, 10mA, 15MHz	2a	Mat	(AF124..126, AF200, 2SA202)
2SA1440	Si-PNP	Lo-sat, 100V, 3A, 15W, <300/1800nS	17c	Nec	2SA1388, 2SA1441, 2SA1741
2SA1441	Si-PNP	Sw, Pow, Lo-sat, 100V, 5A, 25W, <300/1800nS	17c	Nec	2SA1388, 2SA1442, 2SA1741
2SA1442	Si-PNP	Sw, Pow, 100V, 7A, 30W, <300/1800nS	17c	Nec	2SA1443, 2SA1742
2SA1443	Si-PNP	Sw, Pow, 100V, 10A, 30W, <300/1800nS	17c	Nec	2SA1444, 2SA1743
2SA1444	Si-PNP	Sw, Pow, 100V, 15A, 30W, <300/1800nS	17c	Nec	2SA1744
2SA145	Ge-PNP	AM-Pre/Mix/Osc/IF, 15V, Ueb=10V, 10mA, 6MHz	2a	Mat	(AF124..126, AF200, 2SA201..203)
2SA1450	Si-PNP	GenP, 100V, 0,5A, 0,6W, 120MHz	7c	Sanyo	BC640, 2SA965, 2SB647, 2SA1683,..
2SA1451	Si-PNP	60V, 12A, 30W, 70MHz	-		-
2SA1451(A)	Si-PNP	Lo-sat, 60V, 12A, 30W, 70MHz, 300/1200nS	17c	Tos	2SA1568, 2SA1771
2SA1452	Si-PNP	=2SA1451: 80V, 50MHz, 300/1500nS	17c	os	2SA1771
2SA1453	Si-PNP	GenP, 50V, 0,1A, 0,2W, 200MHz	41c	os	BC212, BC257, BC307, BC557..
2SA1455K	Si-PNP	AF, LN, 120V, 0,05A, 140MHz	35a	Rhm	2SA1312, 2SA1587
2SA1455K-E	Si-PNP	-	35	Rhm	→2SA1455K
2SA1455K-R	Si-PNP	-	35	Rhm	→2SA1455K
2SA1455K-S	Si-PNP	-	35	Rhm	→2SA1455K
2SA1458	Si-PNP	HF/Sw, 40V, 0,2A, 0,25W, <70/300nS	40c	Nec	2N3250..51, 2N3905..06
2SA1459	Si-PNP	Sw, 15V, 0,05A, 0,25W, <20/40nS	40c	Nec	2N4258, 2N4313, 2N5056..57
2SA146	Ge-PNP	AM-IF, 20V, 10mA, 20MHz	4g	it	AF124..127, AF200, 2SA218..227
2SA1460	Si-PNP	Sw, 60V, 1A, 1W, <40/100nS	9b	NEC	-
2SA1461	Si-PNP	=2SA1458: SMD	35a	Nec	-
2SA1461-Y22	Si-PNP	-	35	Nec	→2SA1461
2SA1461-Y23	Si-PNP	-	35	Nec	→2SA1461
2SA1461-Y24	Si-PNP	-	35	Nec	→2SA1461
2SA1462	Si-PNP	=2SA1459: SMD	35a	Nec	-
2SA1462-Y33	Si-PNP	-	35	Nec	→2SA1462
2SA1462-Y34	Si-PNP	-	35	Nec	→2SA1462
2SA1463	Si-PNP	=2SA1460: SMD	39b	Nec	-
2SA1463-IK	Si-PNP	-	39	Nec	→2SA1463
2SA1463-IL	Si-PNP	-	39	Nec	→2SA1463
2SA1464	Si-PNP	HF/Sw, 60V, 0,5A, <35/225nS	35a	NEC	-
2SA1465	Si-PNP	Sw, 30V, 1A, 0,75W, <1/2µS	7c	Nec	-
2SA1466	Si-PNP	=2SA1465: 0,35W	40c	Nec	-
2SA1467	Si-PNP	=2SA1465: SMD	35a	Nec	-
2SA1468	Si-PNP	HF/Vid, 180V, 0,1A, 200MHz	35a	Hitachi	BFN25, 2SA1257, 2SA1330
2SA1468-B	Si-PNP	-	35	Hit	→2SA1468
2SA1468-C	Si-PNP	-	35	Hit	→2SA1468
2SA1469	Si-PNP	Sw, Pow, Lo-sat, 80V, 5A, 20W, 100/600nS	17c	Sanyo	2SA1388, 2SA1441, 2SA1741
2SA147	Ge-PNP	AM-Pre/Mix, 20V, 10mA, 30MHz	4g	it	AF124..126, AF200, 2SA218..227
2SA1470	Si-PNP	Sw, Pow, Lo-sat, 80V, 7A, 25W, 100/600nS	17c	Sanyo	2SA1452, 2SA1442, 2SA1742

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2SA1471	Si-PNP	Sw,Pow,Lo-sat,80V,10A,30W,<100/900n	17c	Sanyo	2SA1443,2SA1743
2SA1474	Si-PNP	Vid-Out,Hi-def,80V,0,8A,15W,800MHz	17j$	Sanyo	-
2SA1475	Si-PNP	Vid-Out,Hi-def,120V,0,4A,15W,500MHz	17j$	Sanyo	-
2SA1476	Si-PNP	Vid-Out,Hi-def,200V,0,2A,15W,400MHz	17j$	Sanyo	-
2SA1477	Si-PNP	AF-Driver,180V,0,14A,10W,150MHz	14b	Sanyo	2SA1541,2SA1801,(BF416,BF418)
2SA1478	Si-PNP	Vid-Out,Hi-def,200V,0,1A,5W,150MHz	14b	Sanyo	2SA1540..41,(2SA1380..81,2SA1406..07)
2SA1479	Si-PNP	Vid-Out,Hi-def,300V,0,1A,7W,70MHz	14b	Sanyo	(2SA1353,2SA1381)
2SA148	Ge-PNP	AM-Pre/Mix,20V,10mA,40MHz	4g	it	AF124..126,AF200,2SA218..227
2SA1480	Si-PNP	Vid-Out,Hi-def,300V,0,1A,7W,150MHz	14b	Sanyo	(2SA1353,2SA1381)
2SA1481	Si-PNP	Sw,60V,0,15A,0,25W,<360/1170nS	40c	Sanyo	BC212,BC256,BC556,2N2906..07,..
2SA1482	Si-PNP	AF,LN,150V,0,05A,0,85W	7c(9mm)	hm	2SA1016K,2SA1124
2SA1483	Si-PNP	GenP,60V,0,2A,200MHz	39b	os	-
2SA1483-O	Si-PNP	-	39	Tos	→2SA1483
2SA1483-R	Si-PNP	-	39	Tos	→2SA1483
2SA1483-Y	Si-PNP	-	39	Tos	→2SA1483
2SA1484	Si-PNP	GenP,90V,0,1A,130MHz	35a	Hitachi	2SA1312
2SA1484-D	Si-PNP	-	35	Hit	→2SA1484
2SA1485	Si-PNP	AF,Vid,200V,0,1A,0,2W,160MHz	7c	it	BF421A,BF436..437,2SB1349..
2SA1486	Si-PNP	Sw,Pow,600/600V,1A,15W,<500/5500nS	14h$	Nec	(2SA1379,2SA1413)
2SA1487	Si-PNP	Video-dr,85V,0,05A,1W,500MHz	7c(9mm)	Mat	-
2SA1488	Si-PNP	AF,Sw-Pow,Lo-sat,60V,4A,25W,15MHz	17c	Sak	2SA1307,2SA1469,2SB1134..1135
2SA1488A	Si-PNP	=2SA1488:80V	17c	-	2SA1469,2SB1018
2SA1489	Si-PNP	AF,Sw-Pow,80V,6A,60W,20MHz	18j$	Sak	BD246C,BD546C,2SB688,2SB776..
2SA149	Ge-PNP	AM-Amp,20V,10mA,50MHz	4g	it	AF124..126,AF200,2SA218..227
2SA1490	Si-PNP	AF,Sw-Pow,120V,8A,80W,20MHz	18j$	Sak	BD246D,BD546D,2SB688,2SB816..
2SA1491	Si-PNP	AF,Sw-Pow,140V,10A,100W,20MHz	18j$	Sak	BD246D,2SA1386(A),2SA1294,2SB817
2SA1492	Si-PNP	AF,Sw-Pow,180V,15A,130W,20MHz	18j$	Sak	BD250E,2SA1386A,2SA1294
2SA1493	Si-PNP	AF,Sw-Pow,200V,15A,150W,20MHz	20j$	Sak	2SA1169..1170,2SA1333,2SB756
2SA1494	Si-PNP	AF,Sw-Pow,200V,17A,200W,20MHz	20j$	Sak	2SA1170,2SA1295
2SA1495	Si-PNP	Sw,Pow,400/400V,0,6A,15W,15MHz	?30j$	Mat	2SA1400
2SA1496	Si-PNP	-	35	Sanyo	→2SA1496
2SA1497	Si-PNP-Digital	Sw,50V,0,1A,0,3W,200MHz,R1=10kΩ	40c	Sanyo	AN1A4Z,DTA114TS,RN2011,UN411S,..
2SA1498	Si-PNP	=2SA1495:25W	30j$	Mat	-
2SA1499	Si-PNP	=2SA1495:25W	17c	Mat	2SA1397,2SA1614
2SA15	Ge-PNP	AM-Pre/Mix/Osc,16V,Ueb=0,5V,15mA,12MHz	2a	it	AF124..126,AF200,2SA202
2SA1500	Si-PNP	Sw,Pow,400/400V,5A,40W,15MHz	17j$	Mat	MJE5851..5852
2SA1501	Si-PNP	=2SA1500:Iso	17c	-	-
2SA1502	Si-PNP	-	35	Sanyo	→2SA1502
2SA1503	Si-PNP-Digital	Sw,R1=2,2kΩ,R2=10kΩ,50V,0,1A,0,3W,200MHz	40c	Sanyo	DTA123YS,UN411H
2SA1504	Si-PNP	AF,LN,50V,0,15A,130MHz	35b	Nec	-
2SA1505	Si-PNP	AF-Driver,35V,0,5A,200MHz	35b	Nec	-
2SA1506	Si-PNP	AF,LN,120V,0,1A,100MHz	35b	Nec	-
2SA1507	Si-PNP	TV-AF-Pow,180/160V,1,5A,10W,120MHz	14b	Sanyo	(2SA1249,2SB649)
2SA1508	Si-PNP	-	35	Sanyo	→2SA1508
2SA1509	Si-PNP-Digital	Sw,50V,0,1A,0,3W,200MHz,R1=47kΩ	40c	Sanyo	AN1L4Z,DTA144TS,KSR2012,UN4110,..
2SA151	Ge-PNP	AM-IF,9V,15mA,6MHz	2a	it	AF124..127,AF200,2SA201..203
2SA1510	Si-PNP	-	35	Sanyo	→2SA1510
2SA1511	Si-PNP-Digital	Sw,50V,0,1A,0,3W,200MHz,R1=4,7kΩ	40c	Sanyo	AN1L3Z,DTA143TS,RN2010,UN4116,..
2SA1512	Si-PNP	=2SA1128:0,3W	40c	Mat	→2SA1128
2SA1513	Si-PNP	Sw,Pow,Lo-sat,100V,15A,60W,<300/1800nS	18c	Nec	-
2SA1514	Si-PNP	GenP,120V,0,05A,140MHz	?35d	hm	2SA1325
2SA1514K	Si-PNP	=2SA1514:	35a	-	2SA1312,2SA1566
2SA1514K-E	Si-PNP	-	35	Rhm	→2SA1514K
2SA1514K-R	Si-PNP	-	35	Rhm	→2SA1514K
2SA1514K-S	Si-PNP	-	35	Rhm	→2SA1514K
2SA1515	Si-PNP	40V,1A,0.3W,150MHz	-		-
2SA1515(S)	Si-PNP	GenP,40V,1A,0,5(S=0,3)W,150MHz	7c,41c	hm	BC636,2SB734,2SB909,2SB1116,..
2SA1516	Si-PNP	AF-Pow,180V,12A,130W,25MHz	18j$	os	2SA1294,2SA1386A,2SA1492
2SA1517	Si-PNP	120V,0,1A,100MHz	35b	Nec	-
2SA1518	Si-PNP	-	35	Sanyo	→2SA1518
2SA1519	Si-PNP	-	35	Sanyo	→2SA1519
2SA152	Ge-PNP	AM-Pre/Mix,9V,15mA,10MHz	2a	it	AF124..126,AF200,2SA201..202
2SA1520	Si-PNP	-	35	Sanyo	→2SA1520
2SA1521	Si-PNP	-	35	Sanyo	→2SA1521

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2SA1522	Si-PNP-Digital	R1=R2=10kΩ,50V,0,5A,0,3W,200MHz	40c	Sanyo	DTB114ES,RN2224,UN4123,2SA1526,..
2SA1523	Si-PNP-Digital	Sw,R1=R2=4,7kΩ50V,0,5A,0,3W,200MHz	40c	Sanyo	DTB143ES,RN2223,UN4122,2SA1527,..
2SA1524	Si-PNP-Digital	Sw,R1=2,2kΩ,R2=10kΩ,50V,0,5A,0,3W,200MHz	40c	Sanyo	DTB123YS,RN2227,UN4124,2SA1528,..
2SA1525	Si-PNP-Digital	Sw,R1=R2=2,2kΩ,50V,0,5A,0,3W,200MHz	40c	Sanyo	DTB123ES,RN2222,UN4121,2SA1529,..
2SA1526	Si-PNP-Digital	=2SA1522:0,6W	7c	Sanyo	→2SA1522
2SA1527	Si-PNP-Digital	=2SA1523:0,6W	7c	Sanyo	→2SA1523
2SA1528	Si-PNP-Digital	=2SA1524:0,6W	7c	Sanyo	→2SA1524
2SA1529	Si-PNP-Digital	=2SA1525:0,6W	7c	Sanyo	→2SA1525
2SA153	Ge-PNP	AM-Mix,15V,4mA,60MHz	2a	Nec	AF124..126,AF200,2SA218..227
2SA1530	Si-PNP	GenP,50V,0,1A,200MHz	35a	Hitachi	BC856..857,BCW69..70,BCW89..
2SA1530A	Si-PNP	=2SA1530:60V	35a	it	BC856,BCW89,2SA1620
2SA1530-Q	Si-PNP	-	35	Mit	→2SA1530
2SA1530-R	Si-PNP	-	35	Mit	→2SA1530
2SA1530-S	Si-PNP	-	35	Mit	→2SA1530
2SA1530-T	Si-PNP	-	35	Mit	→2SA1530
2SA1531	Si-PNP	-	35(2mm)	Mat	→2SA1531
2SA1531A	Si-PNP	-	35(2mm)	Mat	→2SA1531A
2SA1531A-R	Si-PNP	-	35(2mm)	Mat	→2SA1531A
2SA1531A-S	Si-PNP	-	35(2mm)	Mat	→2SA1531A
2SA1531A-T	Si-PNP	-	35(2mm)	Mat	→2SA1531A
2SA1531-R	Si-PNP	-	35(2mm)	Mat	→2SA1531
2SA1531-S	Si-PNP	-	35(2mm)	Mat	→2SA1531
2SA1531-T	Si-PNP	-	35(2mm)	Mat	→2SA1531
2SA1532	Si-PNP	-	35(2mm)	Mat	→2SA1532
2SA1532-A	Si-PNP	-	35(2mm)	Mat	→2SA1532
2SA1532-B	Si-PNP	-	35(2mm)	Mat	→2SA1532
2SA1532-C	Si-PNP	-	35(2mm)	Mat	→2SA1532
2SA1533	Si-PNP	GenP,80V,0,5A,1W,85MHz	7c(9mm)	Mat	2SA965,2SB987,2SB1041,2SB1297..
2SA1534	Si-PNP	GenP,30V,1A,1W,200MHz	7c(9mm)	Mat	2SA966,2SB764,2SB892,2SB978
2SA1534A	Si-PNP	=2SA1534:60V	7c(9mm)	-	2SA1315,2SB647,2SB764,2SB1041
2SA1535	Si-PNP	HF/AF-Pow,150V,1A,15W,200MHz	17c	Mat	2SA1306(A,B),2SA1606,2SA1332
2SA1535A	Si-PNP	=2SA1535:180V	17c	-	2SA1306,2SA1606,2SA1859A
2SA1536	Si-PNP	Vid-Out,Hi-def,80V,0,3A,8W,600MHz	14b	Sanyo	(2SA1402)
2SA1537	Si-PNP	Vid-Out,Hi-def,80V,0,5A,10W,700MHz	14b	Sanyo	(2SA1403)
2SA1538	Si-PNP	Vid-Out,Hi-def,120V,0,2A,8W,400MHz	14b	Sanyo	(2SA1404)
2SA1539	Si-PNP	Vid-Out,Hi-def,120V,0,3A,8W,400MHz	14b	Sanyo	(2SA1405)
2SA154	Ge-PNP	AM-IF,15V,4mA,50MHz	2a	Nec	AF124..127,AF200,2SA218..227
2SA1540	Si-PNP	Vid-Out,Hi-def,200V,0,1A,7W,300MHz	14b	Sanyo	2SA1478,(2SA1352,2SA1406)
2SA1541	Si-PNP	Vid-Out,Hi-def,200V,0,2A,7W,300MHz	14b	Sanyo	(2SA1407)
2SA1542	Si-PNP	GenP,60V,0,15A,0,3W,140MHz	7c	hm	BC212,BC256,BC556,2SB725,..
2SA1543	Si-PNP	=2SA1542:	9c	hm	BC212,BC256,BC556,2SB725,..
2SA1544	Si-PNP	Vid-Out,250V,0,1A,0,75W,300MHz	7c	Nec	BF421A,BF436..437,BF492..493,..
2SA1545	Si-PNP	=2SA1544:1W	9b	Nec	BF421A,BF436..437,BF492..493..
2SA1546	Si-PNP	=2SA1544:7W	14h$	Nec	BF418,2SA1353,2SC1381
2SA1547	Si-PNP	=2SA933	9c	hm	→2SA933
2SA1548	Si-PNP	=2SA854:0,3W	9c	hm	→2SA854
2SA1549	Si-PNP-Darl	=2SA790M:Pins=14mm	9c	hm	→2SA790
2SA155	Ge-PNP	AM-IF,15V,4mA,55MHz	2a	Nec	AF124..127,AF200,2SA218..227
2SA1550	Si-PNP	Sw,Pow,400/400V,0,5A,15W,20MHz,	30j$	Mat	2SA1400,2SA1498
2SA1552	Si-PNP	AF,Sw-Pow,180V,1,5A,15W,120MHz	30j$	Sanyo	2SB768,2SB840..842
2SA1553	Si-PNP	AF-Out,230/230V,1SA,150W,25MHz	77j$	os	-
2SA1554	Si-PNP	=2SA785:Pins=14mm	9c	hm	→2SA785
2SA1555	Si-PNP-Darl	=2SA790:Pins=14mm	9c	hm	→2SA790
2SA1556	Si-PNP	=2SA802:Pins=14mm	9c	hm	→2SA802
2SA1557	Si-PNP	=2SA805:Pins=14mm	9c	hm	→2SA805
2SA1558	Si-PNP	=2SA806:Pins=14mm	9c	hm	→2SA806
2SA1559	Si-PNP	=2SA854:0,3W	9c	hm	→2SA854
2SA156	Ge-PNP	AM-IF,15V,4mA,55MHz	2a	Nec	AF124..127,AF200,2SA218..227
2SA1560	Si-PNP	=2SA881:Pins=14mm	9c	hm	→2SA881
2SA1561	Si-PNP	=2SA933	9c	hm	→2SA933
2SA1562	Si-PNP	Hi-beta,Hi-Ueb,Lo-sat,30V,1,2A,B>500	30j$	Sanyo	-
2SA1563	Si-PNP	-	35	Sanyo	→2SA1563
2SA1564	Si-PNP-Digital	Sw,50V,0,1A,0,3W,R1=10kΩ,R2=47kΩ	40c	Sanyo	AN1A4P,DTA114YS,RN2007,UN4114,..
2SA1565	Si-PNP-Digital	=2SA1564:	40f	Sanyo	→2SA1564

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2SA1566	Si-PNP	AF,120V,0,1A,130MHz	35a	it	2SA1312,2SA1566
2SA1566-D	Si-PNP	-	3S	Hit	→2SA1566
2SA1566-E	Si-PNP	-	3S	Hit	→2SA1566
2SA1567	Si-PNP	Lo-sat,50V,12A,35W,40MHz	17c	Sak	2SA1451..52,(2SA1444,2SA1600..01)
2SA1568	Si-PNP+Diode	=2SA1567:60V,±12A	17c	Sak	2SA1451..52,(2SA1444,2SA1600..01)
2SA157	Ge-PNP	AM-Osc,15V,4mA,65MHz	2a	Nec	AF124..126,AF200,2SA218..227
2SA1571	Si-PNP	-	3S	Sanyo	→2SA1571
2SA1572	Si-PNP-Digital	Sw,50V,0,1A,0,3W,R2=47kΩ	40c	Sanyo	DTA144GS
2SA1573	Si-PNP	-	3S	Sanyo	→2SA1573
2SA1574	Si-PNP-Digital	Sw,50V,0,1A,0,3W,R2=22kΩ	40c	Sanyo	DTA124GS
2SA1575	Si-PNP	HF,200V,0,1A,400MHz	39b	Sanyo	BFN17,BFN19
2SA1576	Si-PNP	=2SA1037:	35a(2mm)	hm	2SA1586,2SA1603,2SA1622
2SA1576-Q	Si-PNP	-	35(2mm)	Rhm	→2SA1576
2SA1576-R	Si-PNP	-	35(2mm)	Rhm	→2SA1576
2SA1576-S	Si-PNP	-	35(2mm)	Rhm	→2SA1576
2SA1578	Si-PNP	GenP,LN,120V,0,05A,140MHz	35a(2mm)	Rohm	2SA1587
2SA1579	Si-PNP	=2SA1514:	35a(2mm)	hm	2SA1609,2SA1612,2SB1220
2SA1579-E	Si-PNP	-	35(2mm)	Rhm	→2SA1579
2SA1579-R	Si-PNP	-	35(2mm)	Rhm	→2SA1579
2SA1579-S	Si-PNP	-	35(2mm)	Rhm	→2SA1579
2SA1580	Si-PNP	Vid,70V,0,05A,700MHz	35a	Sanyo	-
2SA1581	Si-PNP	-	3S	Sanyo	→2SA1581
2SA1582	Si-PNP-Digital	Sw,50V,0,1A,200MHz,R1=2,2kΩ	40c	Sanyo	-
2SA1583	Si-PNP	Sw,600/550V,0,1A,<1/4,5μS	39b	Mat	-
2SA1584	Si-PNP	Sw,400/400V,0,1A,0,9W,<1/4μS	7c(9mm)	hm	2SA1372,2SA1584,2SA1760,2SB1363
2SA1585(S)	Si-PNP	GenP,Lo-sat,20V,2A,0,4W,240MHz	41c	hm	2SB738..739,2SB822,2SB892,2SB911..
2SA1586	Si-PNP	GenP,LN,50V,0,15A,150MHz	35a(2mm)	Philips	-
2SA1586-G	Si-PNP	-	35(2mm)	Tos	→2SA1586
2SA1586-O	Si-PNP	-	35(2mm)	Tos	→2SA1586
2SA1586-Y	Si-PNP	-	35(2mm)	Tos	→2SA1586
2SA1587	Si-PNP	GenP,LN,120V,0,1A,100MHz	35a(2mm)	Philips	2SA1578
2SA1587-BL	Si-PNP	-	35(2mm)	Tos	→2SA1587
2SA1587-GR	Si-PNP	-	3S	Tos	→2SA1587
2SA1588	Si-PNP	GenP,35V,0,5A,200MHz	35a(2mm)	Philips	2SA1577
2SA1588-O	Si-PNP	-	35(2mm)	Tos	→2SA1588
2SA1588-Y	Si-PNP	-	35(2mm)	Tos	→2SA1588
2SA1589	Si-PNP	-	3S	Sanyo	→2SA1589
2SA159	Ge-PNP	AM-Pre/Mix,15V,4mA,55MHz	2a	Nec	AF124..126,AF200,2SA218..227
2SA1590	Si-PNP-Digital	Sw,50V,0,1A,0,3W,200MHz,R1=22kΩ	40c	Sanyo	AN1F4Z,DTA124TS,KSR2011,UN4117,..
2SA1591	Si-PNP-Digital	=2SA1590:R1=4,7kΩR2=47kΩ	40c	Sanyo	DTA143ZS,KSR2014,RN2006,2SA1616
2SA1592	Si-PNP	Sw,Pow,120V,1A,10W,120MHz	30j$	Sanyo	2SA1592,2SB844..845,2SB959..960,..
2SA1593	Si-PNP	Sw,Pow,120V,2A,15W,120MHz	30j$	Sanyo	2SB1215..16
2SA1594	Si-PNP	GenP,50V,0,1A,140MHz	35a(2mm)	Rohm	BC856W..857W,2SA1576,2SA1586..
2SA1595	Si-PNP	GenP,50V,0,1A,140MHz	35a	Rohm	BC856..857,BCW69..70,2SA1311..
2SA1596	Si-PNP	AF,Sw,80V,2A,1,2W,<1/4μS	7c(9mm)	hm	2SA1315,2SA1429,2SB1459
2SA1597	Si-PNP	-	3S	Sanyo	→2SA1597
2SA1598	Si-PNP	Lo-sat,60V,7A,25W,50MHz,<0,3/2μS	15c	hi	2SA1442,2SA1470,2SA1742
2SA1599	Si-PNP	Lo-sat,60V,10A,25W,50MHz,<0,3/2μS	15c	hi	2SA1443,2SA1471,2SA1743
2SA15H	Ge-PNP	=2SA15:Ueb=12V	2a	-	-
2SA16	Ge-PNP	AM-Pre/Mix/Osc,12V,15mA,12MHz	2a	it	AF124..126,AF200,2SA202
2SA160	Ge-PNP	AM-Pre/Mix,15V,4mA,55MHz	2a	Nec	AF124..126,AF200,2SA218..227
2SA1600	Si-PNP	Sw,Pow,Lo-sat,60V,12A,30W,<300/2000nS	15c	hi	2SA1451..52,2SA1568
2SA1601	Si-PNP	Lo-sat,60V,15A,45W,50MHz,<0,3/2μS	15c	hi	2SA1444,2SA1744
2SA1602	Si-PNP	=2SA1235:	35a(2mm)	it	2SA1586,2SA1622
2SA1602-E	Si-PNP	-	35(2mm)	Mit	→2SA1602
2SA1602-F	Si-PNP	-	35(2mm)	Mit	→2SA1602
2SA1602-G	Si-PNP	-	35(2mm)	Mit	→2SA1602
2SA1603	Si-PNP	=2SA1530:	35a(2mm)	it	2SA1576,2SA1586,2SA1611
2SA1603-Q	Si-PNP	-	35(2mm)	Mit	→2SA1603
2SA1603-R	Si-PNP	-	35(2mm)	Mit	→2SA1603
2SA1603-S	Si-PNP	-	35(2mm)	Mit	→2SA1603
2SA1603-T	Si-PNP	-	35(2mm)	Mit	→2SA1603
2SA1604	Si-PNP	Dual,60V,0,5A,0,4W,200MHz	-	Sanyo	-
2SA1605	Si-PNP	Vid/Sw,250/250V,0,07A,15W,>50MHz	13j$	Matsushita	(BF616,BF618,BF760..762,BF848,..)

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2SA1606	Si-PNP	AF-Pow,180/160V,1,5A,15W,100MHz	17c	Sanyo	2SA1306A,B,2SA1859A
2SA1607	Si-PNP	Sw,40V,0,15A,<40/205nS	35a	Sanyo	-
2SA1608	Si-PNP	Sw,60V,0,5A,<35/225nS	35a(2mm)	NEC	-
2SA1609	Si-PNP	GenP,160V,0,05A,80MHz	35a(2mm)	Nec	-
2SA1609-01S	Si-PNP	-	3S(2mm)	Nec	→2SA1609
2SA1609-016	Si-PNP	-	3S(2mm)	Nec	→2SA1609
2SA1609-017	Si-PNP	-	3S(2mm)	Nec	→2SA1609
2SA161	Ge-PNP	VHF/UHF,20V,15mA,500MHz	5g	on	AF139,AF239(S)
2SA1610	Si-PNP	Sw,15V,0,05A,<20/40nS	35a(2mm)	NEC	2SA1763
2SA1610-Y33	Si-PNP	-	3S(2mm)	Nec	→2SA1610
2SA1610-Y34	Si-PNP	-	3S(2mm)	Nec	→2SA1610
2SA1611	Si-PNP	GenP,60V,0,1A,180MHz	35a(2mm)	Nec	2SB1218A
2SA1611-M4	Si-PNP	-	3S(2mm)	Nec	→2SA1611
2SA1611-M5	Si-PNP	-	3S(2mm)	Nec	→2SA1611
2SA1611-M6	Si-PNP	-	3S(2mm)	Nec	→2SA1611
2SA1611-M7	Si-PNP	-	3S(2mm)	Nec	→2SA1611
2SA1612	Si-PNP	GenP,120V,0,05A,>50MHz	35a(2mm)	Nec	2SA1578..79,2SB1220
2SA1612-C1S	Si-PNP	-	3S(2mm)	Nec	→2SA1612
2SA1612-C16	Si-PNP	-	3S(2mm)	Nec	→2SA1612
2SA1612-C17	Si-PNP	-	3S(2mm)	Nec	→2SA1612
2SA1612-C18	Si-PNP	-	3S(2mm)	Nec	→2SA1612
2SA1613	Si-PNP	Hi-beta,25V,0,15A,200MHz,B>500	35a(2mm)	NEC	-
2SA1613-M1S	Si-PNP	-	3S(2mm)	Nec	→2SA1613
2SA1613-M16	Si-PNP	-	3S(2mm)	Nec	→2SA1613
2SA1614	Si-PNP	Sw,Pow,400/400V,0,5A,25W,20MHz	17c	Mat	2SA1397,2SA1499
2SA1615	Si-PNP	30V,10A,15W,180MHz	-		-
2SA1615(Z)	Si-PNP	Lo-sat,30V,10A,15W,180MHz,80/520nS	30jS	Nec	2SA1834
2SA1616	Si-PNP-Digital	=2SA1591:	40f	Sanyo	DTA143ZS,KSR2014,RN2006,2SA1591
2SA1617	Si-PNP	GenP,55V,0,1A,280MHz	35a	it	BC856..857,BCW69..70,2SA1311..
2SA1617-B	Si-PNP	-	3S	Hit	→2SA1617
2SA1617-C	Si-PNP	-	3S	Hit	→2SA1617
2SA1618	Si-PNP	Dual,50V,0,15A,>80MHz	45/ba1	os	-
2SA1618-GR	Si-PNP	-	4S	Tos	→2SA1618
2SA1618-Y	Si-PNP	-	4S	Tos	→2SA1618
2SA1619	Si-PNP	GenP,30V,0,5A,1W,200MHz	7c(9mm)	Mat	BC636,2SA1382,2SB910,2SB987..
2SA1619A	Si-PNP	=2SA1619:60V	7c(9mm)	-	BC638,2SA1382,2SA1705,2SB910
2SA162	Ge-PNP	VHF/UHF,20V,15mA,500MHz	5g	on	AF139,AF239(S)
2SA1620	Si-PNP	GenP,80V,0,3A,100MHz	35a	Philips	2SB1198
2SA1620-O	Si-PNP	-	3S	Tos	→2SA1620
2SA1620-Y	Si-PNP	-	3S	Tos	→2SA1620
2SA1621	Si-PNP	GenP,35V,0,8A,120MHz	35a	Philips	BCW67..68,2SB1197
2SA1621-O	Si-PNP	-	3S	Tos	→2SA1621
2SA1621-Y	Si-PNP	-	3S	Tos	→2SA1621
2SA1622	Si-PNP	GenP,55V,0,15A,180MHz	35a(2mm)	Sanyo	2SA1586,2SA1602,2SA1611
2SA1623	Si-PNP-Digital	=2SA1511:	40f	Sanyo	AN1L3Z,DTA143TS,RN2010,UN4116,..
2SA1624	Si-PNP	Vid,300/300V,0,1A,0,5W,70MHz	7c	Sanyo	BF421A,BF436..437,2SA1371..72..
2SA1625	Si-PNP	AF,Sw,400/400V,0,5A,0,75W,<1/6µS	7c	Nec	2SB1074,2SB1488
2SA1626	Si-PNP	AF,Sw,400/400V,2A,1W,<0,5/2,7µS	9b	NEC	2SA1786,(2SA1412)
2SA1627	Si-PNP	AF,Sw,600/600V,1A,1W,<0,5/5,5µS	9b	NEC	(2SA1379,2SA1413)
2SA1628	Si-PNP	GenP,30V,0,1A,280MHz	35a(2mm)	Hitachi	BC856W..858W,2SC1603,2SB1218(A)..
2SA1629	Si-PNP	GenP,55V,0,1A,230MHz	35a(2mm)	it	BC856W..857W,2SC1603,2SB1218A,..
2SA163	Ge-PNP	VHF/UHF,20V,15mA,500MHz	5g	on	AF139,AF239(S)
2SA1630	Si-PNP	=2SA1530:0,3W	41c	it	BC212,BC257,BC307,BC557..
2SA1633	Si-PNP	AF,Sw-Pow,150V,10A,100W,20MHz	16c	hm	(BD246D,2SA1186,2SA1386,2SB817,..)
2SA1634	Si-PNP	AF,Sw-Pow,80V,4A,40W,12MHz	17jS	hm	BD244B,BD538,BD540B,BD952,..
2SA1635	Si-PNP	=2SA1634:30W,Iso	17c	hm	2SA1394,2SA1441,2SB1095,(BD244B,..)
2SA164	Ge-PNP	VHF/UHF,20V,15mA,500MHz	5g	on	AF139,AF239(S)
2SA1640	Si-PNP	Sw,Pow,30V,7A,40W,<1/3,5µS	15jS	Nec	2SA1290..91,2SB896(A),2SB919
2SA1641	Si-PNP	Sw,Pow,Lo-sat,25V,8A,15W,<300/950nS	30jS	Sanyo	2SA1615,2SA1834
2SA1643	Si-PNP	Motor-Dr,Lo-sat,50V,7A,25W,75MHz	17c	Sak	2SA1327,2SA1470..1471
2SA1644	Si-PNP	Lo-sat,150V,5A,30W,<300/1900nS	17jS	Nec	2SA1645,2SA1646
2SA1644-Z	Si-PNP	=2SA1644:	30jS	-	-
2SA1645	Si-PNP	Lo-sat,150V,7A,35W,<300/1900nS	17jS	Nec	2SA1646
2SA1645-Z	Si-PNP	=2SA1645:	30jS	-	-

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2SA1646	Si-PNP	Lo-sat, 150V, 10A, 40W, <300/1900nS	17j$	Nec	-
2SA1646-Z	Si-PNP	=2SA1646:	30j$	-	-
2SA1647	Si-PNP	Lo-sat, 150V, 5A, 18W, <300/1900nS	30j$	Nec	-
2SA1648	Si-PNP	Lo-sat, 100V, 5A, 18W, <300/1800nS	30j$	Nec	(2SB1535)
2SA1649(Z)	Si-PNP	Lo-sat, 40V, 10A, 15W, <300/1800nS	30j$	Nec	(2SB935(A), 2SB936(A))
2SA165	Ge-PNP	VHF/UHF, 20V, 15mA, 500MHz	5g	on	AF139, AF239(S)
2SA1650	Si-PNP	=2SA1644: Iso, 25W	17c	Nec	2SA1651, 2SA1652
2SA1651	Si-PNP	=2SA1645: Iso, 25W	17c	Nec	2SA1652
2SA1652	Si-PNP	=2SA1646: Iso, 30W	17c	Nec	-
2SA1653	Si-PNP	-	3S	Sanyo	→2SC4104
2SA1654	Si-PNP-Digital	Sw, 50V, 0,1A, 0,3W, R1=4,7kΩ R2=10kΩ	40c	Sanyo	AN1L3N, DTA143XS, KSR2005, UN411F
2SA1655	Si-PNP	-	3S	Sanyo	→2SA1665
2SA1656	Si-PNP-Digital	Sw, 50V, 0,1A, 0,3W, R1=R2=4,7kΩ	40c	Sanyo	AN1L3M, DTA143ES, RN2001, UN411L,..
2SA1657	Si-PNP	AF, Sw-Pow, 150V, 1,5A, 20W, 4MHz	17c	Nec	2SA1304, 2SA1306, 2SA1606, 2SB1096..
2SA1658	Si-PNP	AF, Sw-Pow, 30V, 3A, 15W, 100MHz	17c	Nec	2SA1305, 2SA1307, 2SA1440, 2SB1274..
2SA1659	Si-PNP	AF, Sw-Pow, 160V, 1,5A, 20W, 100MHz	17c	Nec	2SA1306A,B, 2SA1332, 2SA1606..
2SA166	Ge-PNP	VHF/UHF, 20V, 15mA, 500MHz	5g	on	AF139, AF239(S)
2SA1660	Si-PNP	GenP, 150V, 0,05A, 120MHz	39b	Nec	2SA1200, 2SB807
2SA1661	Si-PNP	GenP, 120V, 0,8A, 120MHz	39b	Nec	2SA1201, 2SB806, 2SB1025..26
2SA1662	Si-PNP	GenP, 80V, 0,4A, 120MHz	39b	Nec	2SA1202, 2SB767
2SA1663	Si-PNP	GenP, 30V, 1,5A, 120MHz	39b	Nec	2SA1314, 2SB1121, 2SB1313
2SA1664	Si-PNP	GenP, 35V, 0,8A, 120MHz	39b	Nec	BCX51..S3, 2SA1204, 2SA1364, 2SA1734,..
2SA1666	Si-PNP	HF/Sw, 20V, 0,2A, 3S/70nS	35a	Hitachi	-
2SA1667	Si-PNP	TV-AF-Pow, 150/150V, 2A, 25W, 20MHz	17c	Sak	2SA1304, 2SA1306, 2SA1606, 2SB1338..
2SA1668	Si-PNP	=2SA1667: 200/200V	17c	Sak	2SA1306B, 2SB1096, 2SB1530
2SA1669	Si-PNP	UHF, 20V, 50mA, 3000MHz	35a	Sanyo	BFR194, 2SA1424
2SA167	Ge-PNP	HF/Sw, 20V, Ueb=10V, 0,05A, 0,125W, 9MHz	2a	Nec	ASY26..27, ASY48
2SA1670	Si-PNP	AF, Sw-Pow, 80/80V, 6A, 60W, 20MHz	18c	Sak	2SA1803, 2SA1907
2SA1671	Si-PNP	AF, Sw-Pow, 120/120V, 8A, 75W, 20MHz	18c	Sak	2SA1804, 2SA1908
2SA1672	Si-PNP	AF, Sw-Pow, 140/140V, 10A, 80W, 20MHz	18c	Sak	2SA1805, 2SA1909
2SA1673	Si-PNP	AF, Sw-Pow, 180/180V, 15A, 85W, 20MHz	18c	Sak	(2SA1294, 2SA1386A, 2SA1492, 2SA1516,..)
2SA1674	Si-PNP	AF, 80V, 1A, 1W, 120MHz	9c	Mat	BC640, 2SB1130, 2SB1236, 2SB1437..
2SA1676	Si-PNP-Digital	Sw, 50V, 0,1A, 200MHz, R1=R2=47kΩ	35a(2mm)	Sanyo	DTA144EU
2SA1677	Si-PNP-Digital	Sw, 50V, 0,1A, 200MHz, R1=R2=22kΩ	35a(2mm)	Sanyo	DTA142EU
2SA1678	Si-PNP-Digital	Sw, 50V, 0,1A, 200MHz, R1=R2=10kΩ	35a(2mm)	Sanyo	DTA114EU
2SA1679	Si-PNP	Lo-sat, 60V, 5A, 10W, 50MHz, <0,3/2μS	15c	hi	2SA1307, 2SA1469, 2SA1741
2SA168(A)	Ge-PNP	=2SA167: 0,175W	2ao	Nec	ASY26..27, ASY48
2SA1680	Si-PNP	Sw, Lo-sat, 60V, 2A, 0,9W, 100/400nS	7c(9mm)	os	2SA1315, 2SA1382, 2SB892, 2SB1312..
2SA1681	Si-PNP	-	39	Tos	→2SA1681
2SA1682	Si-PNP	CTV-Vid, 300V, 0,05A, 70MHz	35a	os	BF821, BFN27, 2SA1721
2SA1683	Si-PNP	Lo-sat, 100V, 0,5A, 0,3W, 120MHz, 50/580nS	40c	Sanyo	2SA1683, 2SA1708
2SA1684	Si-PNP	AF/HF-Pow, 120/120V, 1,5A, 20W, 150MHz	17c	Nec	2SA1306(A,B), 2SA1393, 2SA1332, 2SB1186+
2SA1685	Si-PNP	Sw, 20V, 0,15A, 400MHz	35a(2mm)	Sanyo	2SA1610, 2SA1763
2SA1687	Si-PNP	Hi-Ueb, 60V, 0,15A, 130MHz	35a(2mm)	Sanyo	(2SA1252)
2SA1688	Si-PNP	-	3S	Sanyo	→2SA1688
2SA1689	Si-PNP	Vid, 300V, 0,05A, 0,5W, 70MHz	7c	Sanyo	BF421(A), BF437, 2SA1371, 2SA1624
2SA169	Ge-PNP	HF/Sw, 20V, Ueb=10V, 0,05A, 0,125W, 15MHz	2a	Nec	ASY26..27, ASY48
2SA1690	Si-PNP	-/400V, 0,1A	39b	hm	2SA1740, 2SA1759
2SA1692	Si-PNP	Hi-beta, Hi-Ueb, Lo-sat, 30V, 2A, 110MHz	?14h$	Sanyo	-
2SA1693	Si-PNP	AF-Pow, 80/80V, 6A, 60W, 20MHz	18j$	Sak	BD246B..F, 2SA1264, 2SB775..776..
2SA1694	Si-PNP	AF-Pow, 120/120V, 8A, 80W, 20MHz	18j$	Sak	2SA1146, 2SA1186, 2SA1264, 2SB688..
2SA1695	Si-PNP	AF-Pow, Lo-sat, 140/140V, 10A, 100W, 20MHz	18j$	Sak	(BD246D..F, 2SA1265, 2SA1645, 2SB817)
2SA1696	Si-PNP	Vid-Pow, 120V, 0,4A, 400MHz	17c	Sanyo	(2SA1475)
2SA1697	Si-PNP	Vid-Pow, 200/200V, 0,2A, 300MHz	17c	Sanyo	(2SA1476)
2SA1698	Si-PNP	HF, Vid, 300/300V, 0,07A, 1,2W, ≥50MHz	14h$	Mat	BF418, BF472, 2SA1353, 2SA1381
2SA1699	Si-PNP	Sw, Dr, 400/400V, 0,2A, 0,6W, 70MHz	7c	Sanyo	2SA1251, 2SA1625, 2SB1074, 2SB1488,..
2SA17	Ge-PNP	HF-Mix, Sw, 12V, Ueb=0,5V, 15mA, 19MHz	2a	it	AF124..127, AF200, 2SA100, 2SA102
2SA170	Ge-PNP	=2SA169: 0,175W	2ao	Nec	ASY26..27, ASY48
2SA1700	Si-PNP	=2SA1699: 10W	30j$	Sanyo	2SA1196, 2SA1233, 2SA1498
2SA1701	Si-PNP	Sw, 15V, 1,5A, 0,9W, 300MHz	9c	Sanyo	2SA966, 2SA1286, 2SA1703
2SA1702	Si-PNP	Sw, 25V, 5A, 1W, 320MHz, 40/210nS	9c	Sanyo	2SA1431, 2SB1288, 2SB1305..07, 2SB1319
2SA1703	Si-PNP	AF, Lo-sat, 30V, 1,5A, 1W, 180MHz	9c	Sanyo	2SB926..927, 2SB892, 2SB1229
2SA1704	Si-PNP	AF, Sw, Lo-sat, 30V, 2,5A, 1W, 150MHz	9c	Sanyo	2SB892, 2SB985, 2SB1433..34
2SA1705	Si-PNP	AF, Sw, Lo-sat, 60V, 1A, 0,9W, 150MHz	9c	Sanyo	2SA1708, 2SB1116, 2SB1437

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2SA1706	Si-PNP	AF,Sw,Lo-sat,60V,2A,1W,150MHz	9c	Sanyo	2SA1315,2SB892,2SB1229
2SA1707	Si-PNP	AF,Sw,Lo-sat,60V,3A,1W,150MHz	9c	Sanyo	2SB985
2SA1708	Si-PNP	AF,Sw,Lo-sat,120V,1A,1W,120MHz	9c	Sanyo	2SB1456
2SA1709	Si-PNP	AF,Sw,Lo-sat,120V,2A,1W,120MHz	9c	Sanyo	-
2SA171	Ge-PNP	HF/Sw,20V,Ueb=10V,0,05A,0,125W,8MHz	2a	Nec	ASY26..27,ASY48
2SA1710	Si-PNP	Vid,Hi-def,300/300V,0,1A,1W,70MHz	9c	Sanyo	2SA1371
2SA1711	Si-PNP	Sw,20V,0,03A,0,2W,15/110nS	41c	os	2N4313,2N5056..57
2SA1712	Si-PNP	=2SA1711:SMD	35a	os	BSR12,2SA1764
2SA1712-O	Si-PNP	-	35	Tos	→2SA1712
2SA1712-R	SI-PNP	-	35	Tos	→2SA1712
2SA1714	Si-PNP-Darl	Sw,Pow,100/100V,±3A,12W,B>2000	14h$	Nec	(BD680,BD682,2N6036)
2SA1715	Si-P-Darl+Di	Sw,Pow,100V,±5A,25W,180MHz,B>2000	15j$	Nec	2SB1339
2SA1716	Si-P-Darl+Di	Sw,Pow,100V,±8A,30W,100MHz,B>4000	15j$	Nec	2SB1343
2SA1717	Si-P-Darl+Di	Sw,Pow,100V,±10A,40W,100MHz,B>4000	15j$	Nec	-
2SA1718	Si-PNP-Darl	=2SA1715:Iso,20W	17c	Nec	2SB1098,2SB1430
2SA1719	Si-PNP-Darl	=2SA1716:Iso,25W	17c	Nec	2SB1099,2SB1431
2SA172	Ge-PNP	=2SA171:0,2A,0,175W	2ao	Nec	ASY26..27,ASY48
2SA1720	Si-PNP-Darl	=2SA1717:Iso,25W	17c	Nec	2SB1432
2SA1721	Si-PNP	Mix,Video,300V,0,1A,55MHz	35a	os	BFN27
2SA1721-O	Si-PNP	-	35	Tos	→2SA1721
2SA1721-R	Si-PNP	-	35	Tos	→2SA1721
2SA1722	Si-PNP-Digital	Sw,50V,0,1A,R1=2,2kΩ,R2=10kΩ	35a(2mm)	Sanyo	DTA123YU
2SA1723	Si-PNP	Vid,Hi-def,30/20V,0,3A,1500MHz	14h$	Sanyo	-
2SA1724	Si-PNP	Vid,Hi-def,30V,0,3A,1500MHz	39b	Sanyo	-
2SA1725	Si-PNP	=2SA1726:Iso,30W	17c	Sak	2SA1442,2SA1470,2SB1097,2SB1290
2SA1726	Si-PNP	AF-Pow,80V,6A,50W,20MHz	17j$	Sak	BD244B..F,BD544B..C,BD800,BD810..
2SA1727(FS)	Si-PNP	Sw,400/400V,0,5A,10W,12MHz	30j$	hm	2SA1400,2SA1772
2SA1728	Si-PNP	Sw,50V,0,5A,350MHz,60/170nS	35a	Sanyo	BSR15..16,2SA1338
2SA1729	Si-PNP	Sw,50V,1,5A,50/150nS	39b	Sanyo	-
2SA173	Ge-PNP	HF/Sw,20V,Ueb=10V,0,05A,0,125W,4MHz	2a	Nec	ASY26..27,ASY48
2SA1730	Si-PNP	Sw,50V,3A,300MHz,50/150nS	39b	Sanyo	-
2SA1731	Si-PNP	Sw,Pow,50V,5A,15W,300MHz,50/150nS	30j$	Sanyo	-
2SA1732	Si-PNP	Sw,Pow,50V,8A,15W,250MHz,50/150nS	30j$	Sanyo	-
2SA1733K	Si-PNP	HF,30V,0,03A,>200MHz	35a	Rohm	BC856..860,BF550,2SA1256..
2SA1733K-M	Si-PNP	-	35	Rhm	→2SA1733K
2SA1733K-N	Si-PNP	-	35	Rhm	→2SA1733K
2SA1733K-P	Si-PNP	-	35	Rhm	→2SA1733K
2SA1734	Si-PNP	Sw,Lo-sat,40V,1,2A,100/300nS	39b	os	2SA1681,2SB1123
2SA1735	Si-PNP	Sw,Lo-sat,60V,1A,100/350nS	39b	os	2SA1681,2SB1122..1123
2SA1736	Si-PNP	Sw,Lo-sat,60V,3A,100/300nS	39b	os	2SB1124
2SA1737	Si-PNP	-	39	Mat	→2SA1737
2SA1738	Si-PNP	Sw,15V,0,05A,1500MHz,12/20nS	35a	Matsushita	BSR12,2SA1764
2SA1738-Q	Si-PNP	-	35	Mat	→2SA1738
2SA1738-R	Si-PNP	-	35	Mat	→2SA1738
2SA1739	Si-PNP	-	35(2mm)	Mat	→2SA1739
2SA1739-Q	Si-PNP	-	35	Mat	→2SA1739
2SA1739-R	Si-PNP	-	35	Mat	→2SA1739
2SA174	Ge-PNP	=2SA173:0,175W	2ao	Nec	ASY26..27,ASY48
2SA1740	Si-PNP	-	39	Sanyo	→2SA1740
2SA1741	Si-PNP	=2SA1441:	17c	Nec	→2SA1441
2SA1742	Si-PNP	=2SA1442:	17c	Nec	→2SA1442
2SA1743	Si-PNP	=2SA1443:	17c	Nec	→2SA1443
2SA1744	Si-PNP	=2SA1444:	17c	Nec	→2SA1444
2SA1745	Si-PNP	Lo-sat,20V,0,5A,400MHz	35a(2mm)	Sanyo	-
2SA1746	Si-PNP	AF,Sw-Pow,Lo-sat,70V,12A,60W,25MHz	18c	Sak	2SB1508..1509
2SA1747	Si-PNP	GenP,50V,0,05A,250MHz	35a	Matsushita	BC856..857,BF550,2SA1256..
2SA1747-Q	Si-PNP	-	35	Mat	→2SA1747
2SA1747-R	Si-PNP	-	35	Mat	→2SA1747
2SA1748	Si-PNP	-	35(2mm)	Mat	→2SA1748
2SA1748-Q	Si-PNP	-	35(2mm)	Mat	→2SA1748
2SA1748-R	Si-PNP	-	35(2mm)	Mat	→2SA1748
2SA1749	Si-PNP	Vid-Out,Hi-def,200V,0,3A,10W,400MHz	14b	Sanyo	2SA1777
2SA175	Ge-PNP	HF,18V,5mA,85MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA1750	Si-PNP	Vid-Out,Hi-def,140V,0,5A,10W,500MHz	14b	Sanyo	-

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2SA1751	Si-PNP	=2SA1749: 20W	17j$	Sanyo	-
2SA1752	Si-PNP	=2SA1750: 20W	17j$	Sanyo	-
2SA1753	Si-PNP	-	3S	Sanyo	→2SA1753
2SA1755	Si-PNP	Sw, 100V, 0,7A, 0,9W, >100MHz, <60/400nS	7c(9mm)	Hit	2SA965, 2SA1013, 2SA1275
2SA1757	Si-PNP	AF, Sw-Pow, Lo-sat, 100V, 5A, 25W, 80MHz	17c	Rhm	2SA1388, 2SA1441, 2SA1741
2SA1758	Si-PNP	AF, Sw-Pow, Lo-sat, 100V, 12A, 30W, 80MHz	17c	Rhm	2SA1444, 2SA1744
2SA1759	Si-PNP	=2SA1760: SMD	39b	Rhm	2SA1740
2SA1759-N	Si-PNP	-	39	Rhm	→2SA1759
2SA1759-P	Si-PNP	-	39	Rhm	→2SA1759
2SA1759-Q	Si-PNP	-	39	Rhm	→2SA1759
2SA176	Ge-PNP	HF, 18V, 5mA, 85MHz	4g	Tos	AF124..126, AF200, 2SA218..227
2SA1760	Si-PNP	Sw, 400/400V, 0,1A, 0,9W, 12MHz	7c(9mm)	Rhm	2SA1372, 2SA1584, 2SB1363
2SA1761	Si-PNP	AF, Sw, 60V, 3A, 0,9W, 100MHz	7c(9mm)	Tos	2SA1707, 2SB985, 2SB1066
2SA1762	Si-PNP	=2SA777:	9c	Mat	→2SA777
2SA1763	Si-PNP	-	3S(2mm)	Sanyo	→2SA1763
2SA1764	Si-PNP	Fast-Sw, 15V, 0,2A, 1GHz, 11/21nS	3Sa	Sanyo	-
2SA1765	Si-PNP	Sw, 15V, 0,2A, 0,3W, 1GHz, <25/60nS	40c	Sanyo	-
2SA1766	Si-PNP	Hi-Ueb, Hi-beta, Lo-sat, 30V, 0,3A	39b	Sanyo	-
2SA1767	Si-PNP	GenP, Vid, 300V, 0,07A, 0,75W, >50MHz	7c	Mat	BF421(A), BF437, BF486, 2SA1371..
2SA1768	Si-PNP	Sw, 180/160V, 0,7A, 1W, 60/960nS	9c	Sanyo	2SA1319, 2SA1770
2SA1769	Si-PNP	=2SA1768: 10W	14b	Rhm	2SA1507, (2SA1248..49)
2SA1770	Si-PNP	Sw, 180/160V, 1,5A, 1W, 40/740nS	9c	Sanyo	(2SB1212)
2SA1771	Si-PNP	AF, Sw-Pow, Hi-Ueb, 80V, 12A, 30W, 50MHz	17c	Tos	-
2SA1772	Si-PNP	Sw, Pow, 400/400V, 1A, 15W, 50MHz	30j$	Sanyo	2SA1379, 2SA1413, 2SA1807
2SA1773	Si-PNP	Sw, Pow, 400/400V, 2A, 15W, 40MHz	30j$	Sanyo	2SA1412
2SA1774(H)	Si-PNP	=2SA1037:	3Sa(1,6mm)	Rhm	2SB1462
2SA1774-FQ	Si-PNP	-	3S(1,6mm)	Rhm	→2SA1774
2SA1774-FR	Si-PNP	-	3S(1,6mm)	Rhm	→2SA1774
2SA1774-FS	Si-PNP	-	3S(1,6mm)	Rhm	→2SA1774
2SA1775	Si-PNP	Sw, Pow, 400/400V, 0,5A, 10W, 12MHz	14h$	Rhm	2SA1156
2SA1776	Si-PNP	=2SA1775:	9c	Rhm	2SA1625, 2SB1074, 2SB1488
2SA1777	Si-PNP	Vid-Out, Hi-def, 250V, 0,3A, 10W, 400MHz	14b	Sanyo	-
2SA1778	Si-PNP	VHF-Osc/Pre, 15V, 50mA, >600MHz	3S	Sanyo	BF569, BF579, BF767
2SA1779	Si-PNP	Sw, 50V, 0,1A, 0,4W, >200MHz	7c	Hit	BC556..557, 2N2906..07, 2SA1015,..
2SA178	Ge-PNP	HF, 18V, 5mA	4g	Tos	AF124..126, AF200, 2SA218..227
2SA1780	Si-PNP	=2SA1775:	7c(9mm)	Rhm	2SA1625, 2SB1074, 2SB1488
2SA1781	Si-PNP	=2SA1782: SMD	3Sa	Sanyo	BC856, BCW89, 2SA1311
2SA1782	Si-PNP	GenP, 55V, 0,15A, 0,3W, 180MHz	40c	Sanyo	BC212, BC256, BC556, 2SA1285(A)..
2SA1783	Si-PNP	=2SA1782: 0,5W	7c	Sanyo	BC212, BC256, BC556, 2SA1285(A)..
2SA1784	Si-PNP	=2SA1699: 1W	9c	Sanyo	→2SA1699
2SA1785	Si-PNP	Sw, Dr, 400/400V, 1A, 1W, 50MHz	9c	Sanyo	2SA1626
2SA1786	Si-PNP	Sw, Dr, 400/400V, 2A, 1W, 40MHz	9c	Sanyo	2SA1626
2SA1787	Si-PNP	Vid, Hi-def, 200/200V, 0,1A, 1W, 150MH	9c	Sanyo	2SA1370..71
2SA1788	Si-PNP	AF, Sw-Pow, -/120V, 8A, 80W	16c	Rhm	2SA1672, 2SA1805, 2SA1909
2SA1789	Si-PNP	AF, Sw-Pow, -/60V, 12A, 80W	16c	Rhm	2SA1909
2SA1790	Si-PNP	-	3S(1,6mm)	Mat	→2SA1790
2SA1790-A	Si-PNP	-	3S(1,6mm)	Mat	→2SA1790
2SA1790-B	Si-PNP	-	3S(1,6mm)	Mat	→2SA1790
2SA1790-C	Si-PNP	-	3S(1,6mm)	Mat	→2SA1790
2SA1791	Si-PNP	-	3S(1,6mm)	Mat	→2SA1791
2SA1791-Q	Si-PNP	-	3S(1,6mm)	Mat	→2SA1791
2SA1791-R	Si-PNP	-	3S(1,6mm)	Mat	→2SA1791
2SA1792	Si-PNP	Sw, Pow, Lo-sat, 50V, 10A, 15W, 45MHz	?30c	Tos	-
2SA1793	Si-PNP	Lo-sat, 60V, 5A, 15W, 60MHz, 100/1100nS	?30c	Tos	(2SA1244, 2SA1795, 2SB1203)
2SA1794	Si-PNP	Lo-sat, 100V, 5A, 15W, 60MHz, 200/1100nS	?30c	Tos	(2SA1648)
2SA1795	Si-PNP	Sw, Pow, Lo-sat, 60V, 5A, 10W, <300/2000nS	30j$	Shi	2SA1244, 2SA1877, 2SB1203
2SA1796	Si-PNP	Sw, Pow, Lo-sat, 60V, 7A, 10W, <300/2000nS	30j$	Shi	2SB1204
2SA1797	Si-PNP	AF, Lo-sat, 50/50V, 2A	39b	Rhm	2SA1681, 2SA1736, 2SB1123..24
2SA1797-P	Si-PNP	-	39	Rhm	→2SA1797
2SA1797-Q	Si-PNP	-	39	Rhm	→2SA1797
2SA1798	Si-PNP	Sw, Pow, Lo-sat, 25V, 8A, 10W, 200MHz	14b	Sanyo	-
2SA1799	Si-PNP	Vid-Out, Hi-def, 180V, 0,3A, 20W, 400MHz	17j$	Tos	S3746
2SA17H	Ge-PNP	=2SA17: 16V, Ueb=12V	2a	-	-
2SA18	Ge-PNP	HF/Sw, 21V, Ueb=0,5V, 15mA, 19MHz	2a	Hit	AF124..127, AF200, 2SA100, 2SA102

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2SA180	Ge-PNP	HF/AF,15V,Ueb=15V,10mA,10MHz	2a	Sanyo	(AF124..127,AF200,2SA202)
2SA1800	Si-PNP	Vid-Out,Hi-def,250V,0,15A,10W,240MHz	17c	Tos	S3751
2SA1801	Si-PNP	=2SA1799:8W	14b	Tos	2SA1749
2SA1802	Si-PNP	Sw,Pow,Lo-sat,30V,3A,10W,180MHz	30j$	Tos	2SB962,2SB1202
2SA1803	Si-PNP	AF-Pow,80V,6A,55W,30MHz	18c	Tos	2SA1670,2SA1907,(BD246A..F)
2SA1804	Si-PNP	AF-Out,120V,8A,70W,30MHz	18c	Tos	2SA1671,2SA1908,(BD246C..F)
2SA1805	Si-PNP	AF-Out,140V,10A,80W,30MHz	18c	Tos	2SA1672,2SA1909,(BD246D..F)
2SA1806	Si-PNP	-	35(1,6mm)	Mat	→2SA1806
2SA1806-Q	Si-PNP	-	35(1,6mm)	Mat	→2SA1806
2SA1806-R	Si-PNP	-	35(1,6mm)	Mat	→2SA1806
2SA1807(FS)	Si-PNP	Sw,Pow,600/600V,1A,10W,200/2200nS	30j$	Rhm	2SA1379,2SA1413
2SA1808	Si-PNP	=2SA1733K:	35a(2mm)	Rhm	BC856W..860W,2SB1218
2SA1808-M	Si-PNP	-	35(2mm)	Rhm	→2SA1808
2SA1808-N	Si-PNP	-	35(2mm)	Rhm	→2SA1808
2SA1808-P	Si-PNP	-	35(2mm)	Rhm	→2SA1808
2SA1809	Si-PNP	Sw,400/400V,0,5A,1,2W,600/3700nS	78b	Rhm	2SA1400,2SA1727
2SA181	Ge-PNP	HF/AF,15V,Ueb=15V,10mA,5MHz	2a	Sanyo	(AF124..127,AF200,2SA201..203)
2SA1810	Si-PNP	Vid-Out,200/200V,0,2A,10W,300MHz	14h$	Hit	2SA1407
2SA1811	Si-PNP	AF,Sw,35V,0,5A,0,8W,200MHz	7c(9mm)	Tos	2SA1533,2SA1683,2SB987,2SB1297
2SA1812	Si-PNP	=2SA1775:SMD	39b	Rhm	-
2SA1813	Si-PNP	-	35(2mm)	Sanyo	→2SA1813
2SA1814	Si-PNP	GenP,30V,0,15A,210MHz,B>500	35	Sanyo	2SA1252
2SA1815	Si-PNP	HF,15V,50mA,750MHz	35a	Sanyo	BF569,BF579,BF767
2SA1815-3	Si-PNP	-	35	Sanyo	→2SA1815
2SA1815-4	Si-PNP	-	35	Sanyo	→2SA1815
2SA1815-5	Si-PNP	-	35	Sanyo	→2SA1815
2SA1816	Si-PNP	GenP,LN,150V,0,05A,0,3W,200MHz	40c	Mat	2SA1016K,2SA1123..1124,2SA1482
2SA1818	Si-PNP	GenP,-/32V,1A,0,9W	7c(9mm)	Rhm	2SA1315,2SB764,2SB892,2SB1041..
2SA1819	Si-PNP	GenP,-/150V,0,05A,0,8W	7c(9mm)	Rhm	BF436,BF423A,2SA1281,2SA1370
2SA182	Ge-PNP	HF/AF,15V,Ueb=15V,10mA,5MHz	2a	Sanyo	(AF124..127,AF200,2SA201..203)
2SA1820	Si-PNP	AF-Dr/Out,-/50V,2A,0,9W	7c(9mm)	Rhm	2SA1315,2SB892,2SB1459
2SA1821	Si-PNP	HF,-/20V,50mA,400MHz	35a(1,6mm)	Rohm	-
2SA1821-M	Si-PNP	-	35(1,6mm)	Rhm	→2SA1821
2SA1821-N	Si-PNP	-	35(1,6mm)	Rhm	→2SA1821
2SA1821-P	Si-PNP	-	35(1,6mm)	Rhm	→2SA1821
2SA1822	Si-PNP	Sw,Pow,400/400V,1A,25W,<1/6µS	17c	Tos	2SA1397
2SA1823	Si-PNP	Lo-sat,25V,8A,200MHz,30/215nS	?12b	Sanyo	-
2SA1824	Si-PNP	Lo-sat,60V,5A,130MHz,50/470nS	?12b	Sanyo	-
2SA1825	Si-PNP	Lo-sat,60V,8A,130MHz,50/470nS	?12b	Sanyo	-
2SA1826	Si-PNP	Lo-sat,120V,3A,130MHz,100/850nS	?12b	Sanyo	-
2SA1827	Si-PNP	Lo-sat,120V,4A,130MHz,100/850nS	?12b	Sanyo	-
2SA1828	Si-PNP	=2SA1352:1,3W,150MHz	?12b	Sanyo	(2SA1380..81)
2SA1829	Si-PNP	=2SA1353:1,5W,150MHz	?12b	Sanyo	(2SA1381)
2SA183	Ge-PNP	HF/AF,15V,Ueb=15V,10mA,16MHz	2a	Sanyo	(AF124..127,AF200,2SA202)
2SA1830	Si-PNP	Sw,400/400V,2A,1,5W,40MHz	?12b	Sanyo	-
2SA1831	Si-PNP	Sw,Pow,800/800V,20mA,25W,10MHz	17j$	Sanyo	-
2SA1832	Si-PNP	AF,LN,50V,0,15A,>80MHz	35a(1,6mm)	Toshiba	2SA1774,2SA1836,2SB1462
2SA1832F	Si-PNP	AF,LN,50V,0,15A,>80MHz	flat	Tos	2SA1774,2SA1836,2SB1462
2SA1832-G	Si-PNP	-	35(1,6mm)	Tos	→2SA1832
2SA1832-Y	Si-PNP	-	35(1,6mm)	Tos	→2SA1832
2SA1833	Si-P-Darl+Di	Sw,Pow,100V,8A,25W,100MHz,B>4000	17c	Nec	2SB1283..84
2SA1834(FS)	Si-PNP	AF-Pow,Lo-sat,30V,10A,10W,150MHz	30j$	Rhm	2SA1615
2SA1835S	Si-PNP	Sw,-/40V,0,2A,0,25W	41c	Rhm	BSW24,2N2906..07(A),2SA1339..
2SA1836	Si-PNP	AF,60V,0,1A,0,2W,>50MHz	35a(1,6mm)	Nec	2SB1462
2SA1836-M4	Si-PNP	-	35(1,6mm)	Nec	→2SA1836
2SA1836-M5	Si-PNP	-	35(1,6mm)	Nec	→2SA1836
2SA1836-M6	Si-PNP	-	35(1,6mm)	Nec	→2SA1836
2SA1836-M7	Si-PNP	-	35(1,6mm)	Nec	→2SA1836
2SA1837	Si-PNP	AF-Pow,230/230V,1A,20W,70MHz	17c	Tos	-
2SA1838	Si-PNP	-	35(2mm)	Sanyo	→2SA1838
2SA1839	Si-PNP	Muting,15V,0,1A,600MHz,Ron=3Ω	35a	Sanyo	-
2SA184	Ge-PNP	HF/AF,15V,Ueb=15V,10mA,3MHz	2a	Sanyo	(AF124..127,AF200,2SA201)
2SA1840	Si-P-Darl+Di	Sw,Pow,100/100V,±5A,1,8W,B>2000	78c	Nec	(→2SA1715)
2SA1841	Si-P-Darl+Di	Sw,Pow,100/100V,8A,1,8W,B>4000	78c	Nec	(→2SA1716)

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2SA1842	Si-P-Darl+Di	Sw,Pow,100/100V,±10A,1,8W,B>4000	78c	Nec	(→2SA1717)
2SA1843	Si-PNP	Lo-sat,100/60V,5A,1,8W,80MHz	78c	Nec	(→2SA1441)
2SA1844	Si-PNP	Lo-sat,100/60V,7A,1,8W,40MHz	78c	Nec	(→2SA1442)
2SA1845	Si-PNP	Lo-sat,150/100V,5A,1,8W,150MHz	78c	Nec	(→2SA1644)
2SA1846	Si-PNP	Lo-sat,150/100V,7A,1,8W,150MHz	78c	Nec	(→2SA1645)
2SA1847	Si-PNP	Lo-sat,150/100V,10A,1,8W,150MHz	78c	Nec	(→2SA1646)
2SA1848	Si-PNP	=2SA1536:1,3W	?12b	Sanyo	(→2SA1536)
2SA1849	Si-PNP	=2SA1537:1,3W	?12b	Sanyo	(→2SA1537)
2SA1850	Si-PNP	=2SA1538:1,3W	?12b	Sanyo	(→2SA1538)
2SA1851	Si-PNP	=2SA1539:1,3W	?12b	Sanyo	(→2SA1539)
2SA1852	Si-PNP	=2SA1540:1,3W	?12b	Sanyo	(→2SA1540)
2SA1853	Si-PNP	=2SA1541:1,3W	?12b	Sanyo	(→2SA1541)
2SA1854	Si-PNP	Sw,25V,5A,1,5W,320MHz,40/210nS	?12b	Sanyo	-
2SA1855	Si-PNP	Sw,60V,4A,1,5W,150MHz,70/480nS	?12b	Sanyo	-
2SA1856	Si-PNP	Sw,Pow,400/400V,4A,30W,<700/2000nS	17c	Tos	2SA1501
2SA1857	Si-PNP	=2SA1815:	35a(2mm)	Sanyo	-
2SA1858	Si-PNP	=2SA1767:1W	7c(9mm)	Mat	2SA1371..72,2SA1584,2SA1760,2SB1363
2SA1859	Si-PNP	TV,AF-Pow,150/150V,2A,20W,60MHz	17c	Sak	2SA1306,2SA1332,2SA1606,2SB1186A
2SA1859A	Si-PNP	=2SA1859:180/180V	17c	-	2SA1306A..B,2SA1606
2SA1860	Si-PNP	AF,Sw-Pow,150/150V,14A,80W,50MHz	18c	Sak	2SA1673
2SA1861	Si-PNP	=2SA1862:1,2W	78b	Rhm	(→2SA1862)
2SA1862(FS)	Si-PNP	Sw,400/400V,2A,10W,18MHz,200/2200nS	30j$	Rhm	2SA1412,2SA1773
2SA1863	Si-PNP	=2SA1815:	35a(1,6mm)	Sanyo	-
2SA1864	Si-PNP-Digital	Muting,15V,0,1A,600MHz,Ron=5Ω,R1=R2=4,7kΩ	35a(1,6mm)	Sanyo	-
2SA1865	Si-PNP-Digital	Muting,15V,0,1A,600MHz,Ron=6Ω,R1=R2=10kΩ	35a(1,6mm)	Sanyo	-
2SA1866	Si-NPN-Digital	Muting,15V,0,05A,600MHz,Ron=10Ω,R1=R2=47kΩ	35a(1,6mm)	Sanyo	-
2SA1867	Si-PNP	SMD	35a(2mm)	Hit	-
2SA1867-B	Si-PNP	-	35(2mm)	Hit	→2SA1867
2SA1867-C	Si-PNP	-	35(2mm)	Hit	→2SA1867
2SA1867-D	Si-PNP	-	35(2mm)	Hit	→2SA1867
2SA1868	Si-PNP	Sw,400/400V,0,6A,10W,180MHz	30j$	Mat	2SA1727,2SA1400
2SA1869	Si-PNP	Pow,50V,3A,10W,100MHz	17c	Tos	2SA1307,2SA1440,2SA1469,2SB1185
2SA1870	Si-PNP	Sw,Pow,Lo-sat,100V,12A,35W,80MHz	30j$	Rhm	-
2SA1871	Si-PNP	Sw,600/600V,1A,30MHz,<0,5/5,5µS	39b	Nec	-
2SA1871-GA1	Si-PNP	-	39	Nec	→2SA1871
2SA1871-GA2	Si-PNP	-	39	Nec	→2SA1871
2SA1871-GA3	Si-PNP	-	39	Nec	→2SA1871
2SA1873	Si-PNP	=2SA1618:	45ba1(2mm)	Tos	-
2SA1873-GR	Si-PNP	-	45(2mm)	Tos	→2SA1873
2SA1873-Y	Si-PNP	-	45(2mm)	Tos	→2SA1873
2SA1875	Si-PNP	=2SA1749:12W	30j$	Sanyo	(→2SA1749)
2SA1876	Si-PNP	Sw,Pow,Lo-sat,80V,3A,10W,50MHz	30j$	Shi	2SB1215..1216
2SA1877	Si-PNP	Sw,Pow,Lo-sat,80V,5A,10W,50MHz	30j$	Shi	2SA1648
2SA1878	Si-PNP	Sw,Pow,Lo-sat,80V,5A,25W,50MHz	15c	Shi	2SA1388,2SA1441,2SA1469,2SA1741
2SA1879	Si-PNP	Sw,Pow,Lo-sat,80V,7A,25W,50MHz	15c	Shi	2SA1442,2SA1470,2SA1742
2SA188	Ge-PNP	HF/AF,12V,15mA,10MHz	2a	Fui	AF124..127,AF200,2SA201..202
2SA1880	Si-PNP	Sw,Pow,Lo-sat,80V,10A,25W,50MHz	15c	Shi	2SA1443,2SA1471,2SA1743
2SA1881	Si-PNP	15V,1A,300MHz	35a	Sanyo	2SB1051K
2SA1881-5	Si-PNP	-	35	Sanyo	→2SA1881
2SA1881-6	Si-PNP	-	35	Sanyo	→2SA1881
2SA1881-7	Si-PNP	-	35	Sanyo	→2SA1881
2SA1882	Si-PNP	15V,1,5A,300MHz	39b	Sanyo	2SA1314,2SA1363,2SA1369,2SA1663,..
2SA1882-S	Si-PNP	-	39	Sanyo	→2SA1882
2SA1882-T	Si-PNP	-	39	Sanyo	→2SA1882
2SA1882-U	Si-PNP	-	39	Sanyo	→2SA1882
2SA1883	Si-PNP	Fast-Sw,15V,0,2A,1000MHz,11/19nS	35a(1,6mm)	Sanyo	-
2SA1884	Si-PNP	Sw,-/400V,0,5A,0,9W	7c(9mm)	Rhm	2SA1625,2SB1074,2SB1488
2SA1885	Si-PNP	HF/Sw,15V,0,1A,650MHz	35a(1,6mm)	Rohm	-
2SA1886	Si-PNP	-	35(2mm)	Rhm	→2SA1886
2SA1887	Si-PNP	AF,Sw-Pow,Lo-sat,80V,10A,45MHz	17c	Tos	2SA1443,2SA1471,2SA1743
2SA1888	Si-PNP	FM-IF,30V,30mA,300MHz	35d	Mat	BF550,2SA1256
2SA1888-B	Si-PNP	-	?3S	Mat	→2SA1888
2SA1888-C	Si-PNP	-	?3S	Mat	→2SA1888
2SA1889	Si-PNP	=2SA1810:Iso,8W	14b	Hit	2SA1749,2SA1777

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2SA189	Ge-PNP	HF/AF, 12V, 15mA, 6MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA1890	Si-PNP	Lo-sat, 80V, 1A, 120MHz	39b	Mat	2SB1115A, 2SB1520
2SA1890-Q	Si-PNP	-	39	Mat	→2SA1890
2SA1890-R	Si-PNP	-	39	Mat	→2SA1890
2SA1891	Si-PNP	GenP, Lo-sat, 60V, 2A, 1,3W, 100MHz	12b	Tos	(2SB1142)
2SA1892	Si-PNP	GenP, 50V, 3A, 1,3W, 100MHz	12b	Tos	-
2SA1893	Si-PNP	Strobo, 35V, 5A, 1,3W, 170MHz	12b	Tos	(2SA1357, 2SB1436)
2SA1896	Si-PNP	25V, 2,5A, 400MHz	39b	Sanyo	2SA1736, 2SB1124, 2SB1518
2SA1896-S	Si-PNP	-	39	Sanyo	→2SA1896
2SA1896-T	Si-PNP	-	39	Sanyo	→2SA1896
2SA1897	Si-PNP	Lo-sat, 30V, 5A, 1W, 180MHz, 400/360nS	9b	NEC	(2SA1431, 2SB1050, 2SB1319, 2SB1398)
2SA1898	Si-PNP	Sw, 15V, 3A, <60/220nS	39b	Sanyo	2SB1301, 2SB1518, 2SB1628
2SA1898-R	Si-PNP	-	39	Sanyo	→2SA1898
2SA1898-S	Si-PNP	-	39	Sanyo	→2SA1898
2SA1899	Si-PNP	GenP, 120V, 0,8A, 1W, 120MHz	9c	Tos	2SA965, 2SA1013, 2SA1319, 2SA1768,..
2SA18H	Ge-PNP	=2SA18: Ueb=12V	2a	-	-
2SA19	Ge-PNP	AM-IF, 12V, 2mA, 50MHz	2a	Nec	AF124..126, AF200, 2SA104
2SA190	Ge-PNP	AM-Pre/Mix, 20V, 15mA, 40MHz	4g	Oki	AF124..126, AF200, 2SA218..227
2SA1900	Si-PNP	Lo-sat, 60V, 1A, 150MHz	39b	Rhm	2SA1364, 2SB1115(A), 2SB1122..23
2SA1900-P	Si-PNP	-	39	Rhm	→2SA1900
2SA1900-Q	Si-PNP	-	39	Rhm	→2SA1900
2SA1900-R	Si-PNP	-	39	Rhm	→2SA1900
2SA1902	Si-PNP	GenP, -/80V, 0,7A, 0,9W	7c(9mm)	Rhm	2SA1013, 2SA1275, 2SB647, 2SB1212
2SA1903	Si-PNP	Lo-sat, -/20V, 3A, 0,9W	7c(9mm)	Rhm	2SB985, 2SB1505
2SA1905	Si-PNP	GenP, Lo-sat, 60V, 5A, 1,3W, 60MHz	12b	Tos	(2SB1267)
2SA1906	Si-PNP	Sw, Pow, Lo-sat, 100V, 5A, 25W, 80MHz	30j$	Rhm	2SA1644-Z
2SA1907	Si-PNP	AF, Sw-Pow, 80V, 6A, 60W, 20MHz	18c	Sak	2SA1670, 2SA1803, (BD246A..F)
2SA1908	Si-PNP	AF, Sw-Pow, 120V, 8A, 75W, 20MHz	18c	Sak	2SA1671, 2SA1804, (BD246C..F)
2SA1909	Si-PNP	AF, Sw-Pow, 140V, 10A, 80W, 20MHz	18c	Sak	2SA1672, 2SA1805, (BD246D..F)
2SA191	Ge-PNP	AM-Mix/Osc, 20V, 15mA, 20MHz	4g	Oki	AF124..126, AF200, 2SA218..227
2SA192	Ge-PNP	AM-IF, 20V, 15mA, 13MHz	4g	Oki	AF124..127, AF200, 2SA218..227
2SA1920	Si-PNP	Sw, 600/600V, 0,1A, 1W, 12MHz	9c	Rhm	-
2SA1923	Si-PNP	Sw, Pow, 400/400V, 0,5A, 10W, 200/2200nS	30j$	Tos	2SA1772
2SA1924	Si-PNP	=2SA1924:	14b	Tos	(2SA1156, 2SA1775)
2SA1925	Si-PNP	=2SA1924: 1,5W(Ta=25°)	12b	Tos	(2SA1156, 2SA1775)
2SA1926	Si-PNP	Lo-sat, 80V, 3A, 1W, 80MHz	9c	Tos	-
2SA1927	Si-PNP	Dual, 50V, 0,1A, 0,2W, 100MHz	5-SIP	Mit	-
2SA1928	Si-PNP	Dual, 100V, 0,05A, 0,2W, 150MHz	5-SIP	Mit	-
2SA1929	Si-PNP	Dual, 100V, 0,1A, 0,2W, 100MHz	5-SIP	Mit	-
2SA193	Ge-PNP	AM-Pre/Mix, 15V, Ueb=12V, 15mA, 13MHz	2a	Oki	(AF124..126, AF200, 2SA202)
2SA1930	Si-PNP	TV, Pow, 180/180V, 2A, 20W, 200MHz	17c	Tos	2SA1306A, 2SA1606, 2SA1859A
2SA1931	Si-PNP	Sw, Pow, Lo-sat, 60V, 5A, 25W, 100/1100nS	17c	Tos	2SA1307, 2SA1387, 2SA1469, 2SA1741..
2SA1932	Si-PNP	GenP, 230/230V, 1A, 1,8W, 70MHz	15c	Tos	2SA1837
2SA1933	Si-PNP	GenP, Lo-sat, 60V, 5A, 1,8W, 60MHz	15c	Tos	2SA1388, 2SA1469..70, 2SA1441
2SA1934	Si-PNP	GenP, Lo-sat, 100V, 5A, 1,8W, 60MHz	15c	Tos	2SA1388, 2SA1441, 2SA1741
2SA1935	Si-PNP	Sw, 15V, 1,5A, 300MHz, 30/120nS	39b	Sanyo	2SA1314, 2SA1363, 2SA1369, 2SA1663,..
2SA1936	Si-PNP	Sw, 15V, 5A, 300MHz, 30/120nS	39b	Sanyo	2SB1302, 2SB1308, 2SB1386
2SA1937	Si-PNP	Sw, Pow, 600/600V, 0,5A, 10W, 35MHz	30j$	Tos	2SA1379, 2SA1413, 2SA1807
2SA1939	Si-PNP	AF-Out, 80/80V, 6A, 60W, 30MHz	18j$	Tos	BD246C, BDV94, 2SA1693, 2SB775..
2SA194	Ge-PNP	AM-IF, 15V, Ueb=12V, 15mA, 7MHz	2a	Oki	(AF124..127, AF200, 2SA201)
2SA1940	Si-PNP	AF-Out, 120/120V, 8A, 80W, 30MHz	18j$	Tos	BD246C, BD546D, 2SA1694, 2SB688..
2SA1941	Si-PNP	AF-Out, 140/140V, 10A, 100W, 30MHz	18j$	Tos	BD246D, 2SA1146, 2SA1186, 2SA1491..
2SA1942	Si-PNP	AF-Out, 180/180V, 12A, 120W, 30MHz	77j$	Tos	2SA1302, 2SB1317, 2SB1429
2SA1943	Si-PNP	AF-Out, 230/230V, 15A, 150W, 25MHz	77j$	Tos	2SA1553
2SA1944	Si-PNP	GenP, 50V, 1A, 90MHz, B=400..1200	39b	Mit	2SA1681, 2SB1115, 2SB1122..1123,..
2SA1945	Si-PNP	GenP, 55V, 0,4A, 150MHz	39b	Mit	2SA1202, 2SA1662, 2SB1122..1123,..
2SA1946	Si-PNP	GenP, 25V, 0,7A, 180MHz	39b	Mit	BCX51..53, 2SA1364, 2SB1734, 2SB804,..
2SA1947	Si-PNP	GenP, 30V, 1A, 100MHz	39b	Mit	BCX51..53, 2SA1681, 2SB1122..1123,..
2SA1948	Si-PNP	GenP, 120V, 0,1A, 200MHz	39b	Mit	2SA1173, 2SA1200, 2SB1045..1047
2SA1949	Si-PNP	Sw, Pow, 490/490V, 0,5A, 10W, 70MHz, B>100	30j$	Mat	2SA1379, 2SA1413, 2SA1807
2SA195	Ge-PNP	AM-IF, 15V, Ueb=12V, 15mA, 4MHz	2a	Oki	(AF124..127, AF200, 2SA203)
2SA1950	Si-PNP	Sw, Pow, 500/500V, 1A, 10W, B>100	30j$	Mat	2SA1379, 2SA1413, 2SA1807
2SA1951	Si-PNP	Sw, Pow, 500/500V, 2A, 10W, B>100	30j$	Mat	-
2SA1952(FS)	Si-PNP	Lo-sat, 100V, 5A, 10W, <300/1800nS	30j$	Rhm	2SA1648

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2SA1953	Si-PNP	GenP, 15V, 0,5A, >80MHz, 40/325nS	35a	Toshiba	BSR15..16, BSS80, 2SA1338, 2SA1464
2SA1954	Si-PNP	=2SA1953:	35a(2mm)	Tos	2SA1588, 2SA1619, 2SB1219, 2SB1475
2SA1955	Si-PNP	=2SA1953: 0,4A	35a(1,6mm)	Tos	-
2SA1958	Si-PNP	Vid-Out, 150/150V, 0,2A, 8W, 500MHz	14b	Hit	2SA1749, 2SA1777
2SA196	Ge-PNP	AM-IF, 15V, Ueb=12V, 15mA, 2,5MHz	2a	Oki	(AF124..127, AF200, 2SA203)
2SA1960	Si-PNP	HF, Vid, 80/80V, 0,3A, 0,62SW, 1,3GHz	7c	Hit	-
2SA1961	Si-PNP	HF, Vid, 200/200V, 70mA, 1W, 30MHz	9c	Mat	BF423A, BF436..437, 2SB1349..
2SA1962	Si-PNP	=2SA1943: 130W	18j$	Tos	2SA1294
2SA1963	Si-PNP	VHF/UHF, 12V, 50mA, 5GHz	35a	Sanyo	BFT93
2SA1963-1	Si-PNP	-	3S	Sanyo	→2SA1963
2SA1963-2	Si-PNP	-	3S	Sanyo	→2SA1963
2SA1963-3	Si-PNP	-	3S	Sanyo	→2SA1963
2SA1964	Si-PNP	AF, Sw-Pow, 160V, 1,5A, 20W, 150MHz	17c	Rhm	2SA1306(A,B), 2SA1606, 2SA1332
2SA1965	Si-PNP	Muting, 15V, 0,1A, Ron=1,2Ω	35a(1,6mm)	Sanyo	-
2SA1966	Si-PNP	Sw, Pow, 500/500V, 0,1A, 10W, 30MHz	30j$	Mat	-
2SA1967	Si-PNP	CRT, Sw-Pow, 900/900V, 10mA, 6MHz	17j$	Sanyo	-
2SA1968(LS)	Si-PNP	=2SA1967: Iso	17c	Sanyo	-
2SA1969	Si-PNP	HF, Fast-Sw, 10/10V, 0,4A, 1,7GHz	39b	Sanyo	-
2SA197	Ge-PNP	AM-IF, 15V, Ueb=15V, 10mA	2a	Oki	(AF124..127, AF200, 2SA202)
2SA1971	Si-PNP	Sw, 400/400V, 0,5A, 3SMHz	39b	Tos	2SA1812
2SA1972	Si-PNP	=2SA1971: 0,9W	7c(9mm)	Tos	2SA1780, 2SB1488
2SA1973	Si-PNP	AF, Lo-sat, 30V, 1A, 150MHz	35a	Sanyo	2SB1051K
2SA1973-5	Si-PNP	-	3S	Sanyo	→2SA1973
2SA1973-6	Si-PNP	-	3S	Sanyo	→2SA1973
2SA1974	Si-PNP	GenP, 40V, 0,5A, 0,5W, 200MHz	7	-	BC327, BC636, 2SB734, 2SB909..910,..
2SA1975	Si-PNP	GenP, 50V, 0,15A, 0,4W, 80MHz	7	-	BC212, BC307, BC556..557, 2SB725..
2SA1976	Si-PNP	GenP, 35V, 0,8A, 0,625W, 130MHz	7	-	BC327, BC636, 2SB734, 2SB909..910,..
2SA1977	Si-PNP	Fast-Sw, UHF, 20V, 0,05A, >6GHz	35a	Nec	NE97733
2SA1978	Si-PNP	Fast-Sw, UHF, 20V, 0,05A, >4GHz	35a	Nec	NE97833
2SA198	Ge-PNP	AM-IF, 15V, 15mA	2a	Oki	AF124..127, AF200, 2SA201..203
2SA1982	Si-PNP	GenP, 150/150V, 0,05A, 1W, 200MHz	9c	Mat	2SA1016K, 2SA1124, 2SA1482, 2SB1348..
2SA1984	Si-PNP	GenP, 35V, 5A, 170MHz	48j	Tos	-
2SA1986	Si-PNP	AF, Sw-Pow, 230V, 15A, 150W, 30MHz	18j$	Tos	2SA1294
2SA1987	Si-PNP	=2SA1986: 180W	77j$	Tos	2SA1553, 2SA1943
2SA1989	Si-PNP	GenP, 50V, 0,1A, 200MHz	-	Mit	-
2SA199	Ge-PNP	AM-Pre/Mix, 15V, 5mA	2a	Oki	AF124..126, AF200, 2SA201..203
2SA1993	Si-PNP	GenP, 50V, 0,2A, 0,3W, 200MHz	41	Mit	BC212, BC307, BC557, 2SB725, 2SA1137+
2SA1994	Si-PNP	GenP, 50V, 0,2A, 0,3W, 200MHz	41	Mit	BC212, BC307, BC557, 2SB725, 2SA1137+
2SA1995	Si-PNP	GenP, 50V, 0,1A, 0,3W, 200MHz	41	Mit	BC214, BC416, BC560, 2SA1136..37..
2SA1998	Si-PNP	AF-Pow, 20V, 2A, 0,6W, 80MHz	41	Mit	2SA1382, 2SB739, 2SB926..27, 2SB1425..
2SA20	Ge-PNP	AM-IF, 12V, 2mA, 55MHz	2a	Nec	AF124..126, AF200, 2SA104
2SA200	Ge-PNP	AM-Pre/Mix, 15V, 5mA	2a	Oki	AF124..126, AF200, 2SA201..203
2SA2002	Si-PNP	AF-Pow, 25V, 0,7A, 0,6W, 180MHz	41	Mit	BC327..328, 2SA1426, 2SB808, 2SB910..
2SA2005	Si-PNP	AF, Sw-Pow, TVVelocity Modulation, 160V, 1,5A, 20W, 150MHz	17c	Rhm	2SA1306, 2SA1332, 2SA1606, 2SB1186A, +
2SA2006	Si-PNP	Lo-sat, 100V, 5A, 25W, <300/1800nS	17c	Rhm	2SA1388, 2SA1441, 2SA1741
2SA2007	Si-PNP	Lo-sat, 100V, 12A, 25W, <300/1800nS	17c	Rhm	2SA1444, 2SA1744
2SA2009	Si-PNP	AF, 120V, 0,02A, 120MHz	35a(2mm)	Mat	2SA1578..79, 2SA1612, 2SB1220
2SA201	Ge-PNP	AM-Pre/Mix, 15V, 15mA, 8MHz	2a	Sanyo	AF124..126, AF200, 2SA101..104
2SA2010	Si-PNP	Sw, Lo-sat, 15V, 2,5A, 180MHz, 35/110nS	35a	Mat	-
2SA2011	Si-PNP	Sw, Lo-sat, 15V, 6A, 35/125nS	39b	Sanyo	-
2SA2012	Si-PNP	Sw, Lo-sat, 30V, 5A, 50/295nS	39b	Sanyo	-
2SA2013	Si-PNP	Sw, Lo-sat, 50V, 4A, 30/245nS	39b	Sanyo	-
2SA2014	Si-PNP	Sw, Lo-sat, 15V, 9A, 30/134nS	39b	Sanyo	-
2SA2015	Si-PNP	Sw, Lo-sat, 30V, 8A, 30/205nS	39b	Sanyo	-
2SA2016	Si-PNP	Sw, Lo-sat, 50V, 7A, 40/250nS	39b	Sanyo	-
2SA2017	Si-PNP	AF-Pow, 80V, 4A, 30W, 12MHz	17c	Rhm	2SA1441, 2SA1635, 2SB1017, 2SB1335..
2SA2018	Si-PNP	AF, 15V, 0,5A, 260MHz	35a(1,6mm)	Rhm	-
2SA202	Ge-PNP	AM-IF, 15V, 15mA, 12MHz	2a	Sanyo	AF124..127, AF200, 2SA101..104
2SA2022	Si-PNP	Lo-sat, 60V, 7A, 18W, 290MHz, 30/265nS	17c	Sanyo	2SA1442, 2SA1470, 2SA1742, 2SB1467
2SA2023	Si-PNP	Lo-sat, 80V, 5A, 10W, 100MHz, 100/600nS	14b	Sanyo	-
2SA2025	Si-PNP	Sw, Lo-sat, 15V, 3A, 0,55W, 30/100nS	40c	Sanyo	-
2SA203	Ge-PNP	AM-IF, 15V, 15mA, 5MHz	2a	Sanyo	AF124..127, AF200, 2SA101..104
2SA2031	Si-PNP	AF, Sw-Pow, 250V, 15A, 140W, 10MHz	18j$	Sanyo	2SA1294, 2SA1986
2SA204	Ge-PNP	HF/Sw, 30V, Ueb=20V, 0,2A, 0,15W, 6MHz	2a&	Nec	ASY26..27, ASY48

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2SA205	Ge-PNP	HF/Sw,30V,Ueb=20V,0,2A,0,2W,5MHz	2a&	Nec	ASY26..37,ASY48
2SA206	Ge-PNP	HF/Sw,30V,Ueb=20V,0,2A,0,2W,7MHz	2a&	Nec	ASY26..27,ASY48
2SA207	Ge-PNP	HF/Sw,30V,Ueb=20V,0,2A,0,2W,12MHz	2a&	Nec	ASY26..27,ASY48
2SA208	Ge-PNP	Sw,20V,Ueb=12V,0,4A,0,12W,>3MHz	2a	Hit	ASY76..77
2SA209	Ge-PNP	Sw,20V,Ueb=12V,0,4A,0,12W,>5MHz	2a	Hit	ASY76..77
2SA21	Ge-PNP	AM-IF,12V,2mA,55MHz	2a	Nec	AF124..126,AF200,2SA104
2SA210	Ge-PNP	Sw,20V,Ueb=12V,0,4A,0,12W,>10MHz	2a	Hit	ASY76..77
2SA211(H)	Ge-PNP	Sw,18V,Ueb=10V,0,1A,0,12W,>4MHz	2a	Hit	ASY26..27,ASY48
2SA212(H)	Ge-PNP	=2SA211:25V,Ueb=12V	2a	Hit	ASY26..27,ASY48
2SA213	Ge-PNP	FM-Preamp/Mix,15V,2mA,140MHz	2a	Nec	AF124..125,AF106,AF306,2SA342
2SA214	Ge-PNP	FM-Osc/IF,15V,2mA,140MHz	2a	Nec	AF124..126,AF106,AF306,2SA342
2SA215	Ge-PNP	FM-IF,15V,2mA,120MHz	2a	Nec	AF124..126,AF106,AF306,2SA340..342
2SA216	Ge-PNP	FM-IF,15V,2mA,120MHz	2a	Nec	AF124..126,AF106,AF306,2SA340..342
2SA217(H)	Ge-PNP	HF/Sw,25V,Ueb=12V,0,1A,0,12W,14MHz	2a	Hit	ASY26..27,ASY48
2SA218	Ge-PNP	HF/AF,20V,10mA,55MHz	4g	Sanyo	AF124..126,AF200,2SA102..104
2SA219	Ge-PNP	FM-IF,20V,15mA,55MHz	2a	Sanyo	AF124..126,AF200,2SA103..104
2SA22	Ge-PNP	HF/AF,20V,20mA,12MHz	2a	Fui	AF124..127,AF200,2SA201..202
2SA220	Ge-PNP	AM-Pre/Mix/Osc,20V,15mA,60MHz	2a	Sanyo	AF124..126,AF200,2SA104
2SA221	Ge-PNP	AM-Pre/Mix/Osc,20V,15mA,55MHz	2a	Sanyo	AF124..126,AF200,2SA104
2SA222	Ge-PNP	AM-Pre/Mix/Osc,20V,15mA,60MHz	2a	Sanyo	AF124..126,AF200,2SA104
2SA223	Ge-PNP	AM-Osc,20V,15mA,65MHz	2a	Sanyo	AF124..126,AF200,2SA104
2SA224	Ge-PNP	AM-Pre/Mix/Osc,20V,10mA,90MHz	4g	Sanyo	AF124..126,AF200,2SA104
2SA225	Ge-PNP	AM-Pre/Mix/Osc,20V,15mA,55MHz	2a	Sanyo	AF124..126,AF200,2SA103..104
2SA226	Ge-PNP	AM-Pre/Mix,15V,10mA,95MHz	4g	Sanyo	AF124..126,AF200,2SA104
2SA227	Ge-PNP	AM-Pre/Mix/Osc,20V,10mA,90MHz	4g	Sanyo	AF124..126,AF200,2SA104
2SA228	Ge-PNP	HF,80V,0,05A,0,17W,35MHz	4g	Sanyo	AF118,SFT162,2SA358
2SA229	Ge-PNP	VHF/UHF,20V,5mA,400MHz	5g	Tos	AF139,AF239(S)
2SA23	Ge-PNP	HF/AF,20V,15mA,8MHz	2a	Fui	AF124..127,AF200,2SA201..203
2SA230	Ge-PNP	VHF/UHF,20V,5mA,400MHz	5g	Tos	AF139,AF239(S)
2SA231	Ge-PNP	AF/HF/Sw,40V,0,4A,3W(Tc=25°),2,5MHz	2a	Hit	(AD162)
2SA232	Ge-PNP	AF/HF/Sw,30V,0,4A,3W(Tc=25°),4MHz	2a	Hit	(AD162)
2SA233	Ge-PNP	AM-IF,20V,10mA,100MHz	4g	Hit	AF124..127,AF200,2SA342
2SA234(H)	Ge-PNP	AM-IF,20V,10mA,120MHz	4g	Hit	AF124..127,AF200,2SA342
2SA235(H)	Ge-PNP	FM-Preamp/Mix/Osc,20V,10mA,135MHz	4g	Hit	AF124..125,AF200,AF106,AF306
2SA236	Ge-PNP	AM-Pre/Mix/Osc/IF,18V,5mA,35MHz	4g	Tos	AF124..126,AF200,2SA101..104
2SA237	Ge-PNP	AM-Pre/Mix/Osc/IF,18V,5mA,35MHz	4g	Tos	AF124..126,AF200,2SA101..104
2SA238	Ge-PNP	VHF/UHF,25V,30mA,700MHz	2a	Nec	(AF139,AF239(S))
2SA239	Ge-PNP	FM/VHF,20V,5mA,200MHz	5g	Tos	AF106,AF109R,AF139,AF239(S)
2SA24	Ge-PNP	HF,30V,10mA,100MHz	5g	Fui	AF124..126,AF200,AF239,2SA104
2SA240	Ge-PNP	FM/VHF,20V,5mA,200MHz	5g	Tos	AF106,AF109R,AF139,AF239(S)
2SA241	Ge-PNP	FM/VHF,20V,5mA,200MHz	1g	Mat	AF106,AF109R,AF139,AF239(S)
2SA242	Ge-PNP	FM/VHF,20V,5mA,250MHz	1g	Mat	AF106,AF109(R),AF139,AF239(S)
2SA243(A)	Ge-PNP	FM/VHF,20V,5mA,300MHz	1g	Mat	AF109R,AF139,AF239(S)
2SA244(A)	Ge-PNP	FM/VHF,25V,30mA,600MHz	2a	Nec	AF109R,AF139,AF239(S)
2SA245	Ge-PNP	FM/VHF,25V,30mA,700MHz	2a	Nec	AF109(R),AF139,AF239(S)
2SA246(H)	Ge-PNP	FM/VHF,30V,30mA,160MHz	4g	Hit	AF106,AF109R,AF139,AF239(S)
2SA247	Ge-PNP	HF/Sw,10V,0,03A,0,1W,200MHz	4g	Hit	ASZ21,2N2955..2957
2SA248	Ge-PNP	Sw,40V,0,2A,0,1W,40MHz,-/250n5	4g	Tos	ASZ21,2N2955..2957
2SA249	Ge-PNP	HF,100V,10mA,0,11W,50MHz,B=60	2a	Mat	AF118,SFT162,2SA358
2SA25	Ge-PNP	HF,30V,15mA,100MHz	5g	Fui	AF124..126,AF200,AF239,2SA104
2SA250	Ge-PNP	=2SA249:a=100	2a	-	AF118,SFT162,2SA358
2SA251	Ge-PNP	Sw,15V,Ueb=15V,0,05A,0,05W,50MHz	2a	Fui	ASZ21,2N2955..2957
2SA252	Ge-PNP	Sw,15V,0,05A,0,05W,80MHz	2a	Fui	ASZ21,2N2955..2957
2SA253	Ge-PNP	VHF/UHF,20V,30mA,450MHz	2a	Fui	AFY18,(AF139,AF239(S))
2SA254	Ge-PNP	AM-Pre/Mix/Osc,12V,10mA,10MHz	37a	Fui	AF124..126,AF200,2SA201..202
2SA255	Ge-PNP	AM-IF,12V,10mA,5MHz	37a	Fui	AF124..126,AF200,2SA201..203
2SA256	Ge-PNP	AM-Pre/Mix/Osc,20V,10mA,60MHz	37a	Fui	AF124..126,AF200,2SA104
2SA257	Ge-PNP	AM-Pre/Mix/Osc,20V,10mA,50MHz	37a	Fui	AF124..126,AF200,2SA104
2SA258	Ge-PNP	AM-Osc,20V,10mA,40MHz	37a	Fui	AF124..126,AF200,2SA103..104
2SA259	Ge-PNP	AM-Pre/Mix/Osc,20V,10mA,30MHz	37a	Fui	AF124..126,AF200,2SA103..104
2SA26	Ge-PNP	HF,20V,Ueb=15V,50mA,6MHz	2a	Nec	(AF121S,AF202(S),AFY18)
2SA260	Ge-PNP	FM/VHF,20V,10mA,300MHz	5g	Sanyo	AF109R,AF139,AF239(S)
2SA261	Ge-PNP	FM/VHF,20V,10mA,300MHz	5g	Sanyo	AF109R,AF139,AF239(S)
2SA262	Ge-PNP	FM/VHF,20V,10mA,450MHz	5g	Sanyo	AF139,AF239(S)

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2SA263	Ge-PNP	FM/VHF, 20V, 10mA, 500MHz	5g	Sanyo	AF139, AF239(S)
2SA264	Ge-PNP	FM/VHF, 20V, 10mA, 450MHz	5g	Sanyo	AF139, AF239(S)
2SA265	Ge-PNP	FM/VHF, 20V, 10mA, 300MHz	5g	Sanyo	AF109R, AF139, AF239(S)
2SA266	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 60MHz	2a	Fui	AF124..126, AF200, 2SA104
2SA267	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 50MHz	2a	Fui	AF124..126, AF200, 2SA104
2SA268	Ge-PNP	AM-Osc, 20V, 10mA, 40MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA269	Ge-PNP	AM, 20V, 10mA, 30MHz	2a	Fui	AF124..126, AF200, 2SA102..104
2SA27	Ge-PNP	HF, 18V, 5mA, 50MHz	4g	Tos	AF124..126, AF200, AF239, 2SA104
2SA270	Ge-PNP	AM-Pre/Mix, 9V, 10mA, 50MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA271	Ge-PNP	AM-Pre/Mix, 9V, 10mA, 30MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA272	Ge-PNP	AM-IF, 9V, 10mA, 20MHz	2a	Fui	AF124..127, AF200, 2SA102..104
2SA273	Ge-PNP	AM-Pre/Mix/Osc, 34V, 10mA, 40MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA274	Ge-PNP	AM-IF, 34V, 10mA, 30MHz	2a	Fui	AF124..127, AF200, 2SA102..104
2SA275	Ge-PNP	AM-Pre/Mix/Osc, 34V, 10mA, 45MHz	2a	Fui	AF124..126, AF200, 2SA103..104
2SA276	Ge-PNP	Fast-Sw, 15, 0,03A, 0,075W, 210MHz, -/3,2nS	5g	Tos	ASZ21, 2N2955..2957
2SA277	Ge-PNP	Sw, 18V, 0,04A, 0,065W, >3,5MHz, -/450nS	2a	Tos	ASY26..27, ASY48
2SA278	Ge-PNP	Sw, 18V, 0,04A, 0,065W, >11MHz, -/400nS	2a	Tos	ASY26..27, ASY48
2SA279	Ge-PNP	AM/FM, 30V, 30mA, 150MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA28	Ge-PNP	HF, 18V, 5mA, >60MHz	4g	Tos	AF124..126, AF200, AF239, 2SA104
2SA280	Ge-PNP	AM/FM, 30V, 30mA, 70MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA281	Ge-PNP	AM/FM, 30V, 30mA, 100MHz	1g	Mat	AF124..126, AF200, AF106, AF109R
2SA282	Ge-PNP	Sw, 18V, Ueb=12V, 0,2A, 0,15W, 6MHz	2a	Tos	ASY26..27, ASY48
2SA283	Ge-PNP	Sw, 18V, Ueb=12V, 0,2A, 0,15W, 10MHz	2a	Tos	ASY26..27, ASY48
2SA284	Ge-PNP	Sw, 18V, Ueb=12V, 0,2A, 0,15W, 14MHz	2a	Tos	ASY26..27, ASY48
2SA285	Ge-PNP	AM-Mix/Osc/IF, 18V, 5mA, 40MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA286	Ge-PNP	AM-Pre/Mix, 18V, 5mA, 50MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA287	Ge-PNP	AM-Pre/Mix, 18V, 5mA, 60MHz	4g	Nec	AF124..126, AF200, 2SA103..104
2SA288	Ge-PNP	FM/VHF, 20V, 10mA, 330MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA2883-O	Si-PNP	-	39	Tos	→2SA2883
2SA2883-Y	Si-PNP	-	39	Tos	→2SA2883
2SA289	Ge-PNP	FM/VHF, 20V, 10mA, 350MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA29	Ge-PNP	HF, 18V, 5mA, 35MHz	4g	Tos	AF124..126, AF200, AF239, 2SA104
2SA290	Ge-PNP	FM/VHF, 20V, 10mA, 370MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA291	Ge-PNP	FM/VHF, 20V, 50mA, 100MHz	2a	Fui	AF106, AF109R, AF139, AF239(S)
2SA292	Ge-PNP	FM/VHF, 15V, 50mA, 200MHz	2a	Fui	AF106, AF109R, AF139, AF239(S)
2SA293	Ge-PNP	FM/VHF, 15V, 50mA, 300MHz	2a	Fui	AF109R, AF139, AF239(S)
2SA294	Ge-PNP	FM/VHF, 15V, 50mA, 400MHz	2a	Fui	AF109R, AF139, AF239(S)
2SA295	Ge-PNP	FM/VHF, 15V, 50mA	2a	Fui	AF109R, AF139, AF239(S)
2SA296	Ge-PNP	HF, 15V, 15mA, 5MHz	2a	old	AF124..127, AF200, 2SA101..104
2SA297	Ge-PNP	HF, 16V, 15mA, 10MHz	2a	old	AF124..127, AF200, 2SA101..104
2SA298	Ge-PNP	HF, 40V, 10mA, 35MHz	4g	old	AF124..127, AF200, 2SA101..104
2SA299	Ge-PNP	AM-IF, 15V, 10mA	2a	Sanyo	AF124..127, AF200, 2SA102..104
2SA30	Ge-PNP	HF, 12V, 10mA, 10MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA300	Ge-PNP	AM-IF, 15V, 10mA	2a	Sanyo	AF124..127, AF200, 2SA102..104
2SA301	Ge-PNP	HF/Sw, 30V, 30mA, 100MHz	1g	Mat	AF121(S), AF202(S)
2SA302	Ge-PNP	Sw, 20V, Ueb=15V, 0,1A, 0,083W, 6MHz	1a	Mat	ASY26..27, ASY48
2SA303	Ge-PNP	Sw, 20V, Ueb=15V, 0,1A, 0,083W, 9MHz	1a	Mat	ASY26..27, ASY48
2SA304	Ge-PNP	AM-IF, 18V, Ueb=12V, 40MHz, 4,5MHz	2a	Tos	(AF124..127, AF200, 2SA102..104)
2SA305	Ge-PNP	AM-Pre/Mix/Osc, 18V, Ueb=12V, 40mA, 10MHz	2a	Tos	(AF124..126, AF200, 2SA102..104)
2SA306	Ge-PNP	HF, 40V, 10mA, 55MHz	4g	old	AF124..126, AF200, 2SA103..104
2SA307	Ge-PNP	HF, 40V, 10mA, 75MHz	4g	old	AF124..126, AF200, 2SA103..104
2SA308	Ge-PNP	VHF/UHF, 20V, 5mA, 450MHz	1g	Mat	AF139, AF239(S)
2SA309	Ge-PNP	VHF/UHF, 20V, 5mA, 600MHz	1g	Mat	AF139, AF239(S)
2SA31	Ge-PNP	HF, 12V, 10mA, 5MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA310	Ge-PNP	VHF/UHF, 32V, 25mA, 650MHz	1g	Mat	AF139, AF239(S)
2SA311	Ge-PNP	Sw, 40V, 0,4A, 0,15W, 50MHz, -/330nS	2a	Tos	ASY76..77
2SA312	Ge-PNP	Sw, 40V, 0,2A, 0,15W, 50MHz, -/320nS	2a	Tos	ASY48, ASY76..77
2SA313	Ge-PNP	AM-Pre/Mix/Osc, 18V, 20mA, 40MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA314	Ge-PNP	AM-Pre/Mix/Osc, 18V, 20mA, 40MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA315	Ge-PNP	AM-Pre/Mix/Osc, 18V, 20mA, 55MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA316	Ge-PNP	AM-Pre/Mix/Osc, 18V, 20mA, 75MHz	2a	Tos	AF124..126, AF200, 2SA103..104
2SA32	Ge-PNP	HF/AF, 20V, Ueb=10V, 50mA, 10MHz	2a	Fui	(AF121S, AF202(S), AFY18)
2SA321	Ge-PNP	AM-Pre/Mix/Osc/IF, 20V, 15mA, 30MHz	4g	Sanyo	AF124..126, AF200, 2SA103..104
2SA322	Ge-PNP	AM-Pre/Mix/Osc/IF, 20V, 15mA, 35MHz	4g	Sanyo	AF124..126, AF200, 2SA103..104

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2SA323	Ge-PNP	AM-Pre/Mix/Osc/IF, 20V, 15mA, 40MHz	4g	Sanyo	AF124..126, AF200, 2SA103..104
2SA324	Ge-PNP	AM-Pre/Mix/Osc/IF, 20V, 15mA, 55MHz	4g	Sanyo	AF124..126, AF200, 2SA103..104
2SA325	Ge-PNP	Sw, 20V, Ueb=15V, 0,08A, 0,08W, 5MHz	2a	old	ASY26..27, ASY48
2SA326	Ge-PNP	Sw, 20V, Ueb=15V, 0,08A, 0,08W, 10MHz	2a	old	ASY26..27, ASY48
2SA327	Ge-PNP	Sw, 40V, 0,08A, 0,08W, 35MHz, -/1600nS	4g	old	ASY48, 2N2955..2957
2SA328	Ge-PNP	HF/AF, 20V, 10mA	4g	Sanyo	AF124..127, AF200, 2SA101..104
2SA329	Ge-PNP	HF/AF, 20V, 10mA, 5,5MHz	2a	Sanyo	AF124..127, AF200, 2SA102..104
2SA33	Ge-PNP	HF/AF, 20V, Ueb=10V, 25mA, 6MHz	2a	Fui	(AF121S, AF202(S), AFY18)
2SA330	Ge-PNP	HF/AF, 20V, 10mA	2a	Sanyo	AF124..127, AF200, 2SA102..104
2SA331	Ge-PNP	HF/AF, 40V, 50mA, >40MHz	2a	Sanyo	AF124..127, AF200, 2SA103..104
2SA332	Ge-PNP	HF-Pre, 20V, 10mA, 60MHz	4g	Sanyo	AF124..126, AF200, 2SA104
2SA333	Ge-PNP	HF-Osc, 20V, 10mA, 55MHz	4g	Sanyo	AF124..126, AF200, 2SA104
2SA334	Ge-PNP	HF-Mix, 20V, 10mA, 65MHz	4g	Sanyo	AF124..126, AF200, 2SA104
2SA336	Ge-PNP	AM-IF, 9V, 10mA, 30MHz	4g	Hit	AF124..127, AF200, 2SA102..104
2SA337	Ge-PNP	AM-Pre/Mix/Osc, 9V, 10mA, 35MHz	4g	Hit	AF124..126, AF200, 2SA102..104
2SA338	Ge-PNP	HF, 20V, 5mA, 15MHz	37a	Mat	AF124..127, AF200, 2SA101..104
2SA339	Ge-PNP	HF, 20V, 5mA, 30MHz	37a	Mat	AF124..127, AF200, 2SA101..104
2SA340	Ge-PNP	FM-V/M/O, 20V, 10mA, 70MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA341	Ge-PNP	FM-V/M/O, 20V, 10mA, 70MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA342	Ge-PNP	FM-Preamp/Mix/Osc, 20V, 10mA, 100MHz	5g	Mat	AF124..125, AF200, 2SA260..265
2SA343	Ge-PNP	FM/VHF, 20V, 5mA, 100MHz	1g	Mat	AF106, AF109R, AF139, AF239(S)
2SA344	Ge-PNP	FM, 30V, 30mA, 100MHz	4g	Mat	AF124..125, AF106, AF109R, 2SA342
2SA345	Ge-PNP	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA346	Ge-PNP	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA347	Ge-PNP	FM/VHF, 20V, 10mA, >250MHz	5g	Mit	AF109R, AF139, AF239(S), 2SA260..265
2SA348	Ge-PNP	FM, 20V, 10mA, >200MHz	5g	Mit	AF106, AF109R, AF139, AF239(S)
2SA349	Ge-PNP	FM, 20V, 10mA, >100MHz	5g	Mit	AF106, AF109R, AF139, AF239(S)
2SA35	Ge-PNP	HF, 16V, 15mA, 10MHz	2a	Fui	AF124..127, AF200, 2SA201..202
2SA350(A,H)	Ge-PNP	AM-Pre/Mix/Osc, 20(H=30)V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA351(A,B)	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA352(A,B)	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 40MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA353(A)	Ge-PNP	AM-IF, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA354(A)	Ge-PNP	AM-Pre/Mix/Osc, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA355(A)	Ge-PNP	AM-Pre/Mix/Osc, 25(A=50)V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA356	Ge-PNP	AM-IF, 9V, 10mA, 25MHz	2a	Hit	AF124..127, AF200, 2SA218..227
2SA357	Ge-PNP	AM-Pre/Mix/Osc, 9V, 10mA, 30MHz	2a	Hit	AF124..126, AF200, 2SA218..227
2SA358	Ge-PNP	HF, 75V, 50mA, 40MHz	2ao	Hit	AF118, SFT162
2SA359	Ge-PNP	VHF, 20V, 20mA, 300MHz	2a	Sanyo	AF109R, AF139, AF239(S)
2SA36	Ge-PNP	IF, 16V, 15mA, 5MHz	2a	Fui	AF124..127, AF200, 2SA201..203
2SA360	Ge-PNP	AM/FM, 20V, 10mA, 110MHz	4g	Mit	AF124..125, AF200, 2SA342
2SA361	Ge-PNP	AM/FM, 20V, 10mA, 125MHz	4g	Mit	AF124..125, AF200, 2SA342
2SA362	Ge-PNP	FM, 30V, 30mA, 150MHz	4g	Mit	AF124..125, AF200, AF106, AF109R
2SA363	Ge-PNP	Sw, 10V, 0,03A, 0,1W, 150MHz, -/400nS	4g	Mit	ASZ21, 2N2955..2957
2SA364	Ge-PNP	AM-Pre/Mix, 9V, 10mA, 45MHz	4g	Mit	AF124..126, AF200, 2SA218..227
2SA365	Ge-PNP	AM-Mix/Osc, 9V, 10mA, 50MHz	4g	Mit	AF124..126, AF200, 2SA218..227
2SA366	Ge-PNP	AM-Pre/Mix, 9V, 10mA, 75MHz	4g	Mit	AF124..126, AF200, 2SA218..227
2SA367	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 30MHz	2a	Mit	AF124..126, AF200, 2SA218..227
2SA368	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 40MHz	2a	Mit	AF124..126, AF200, 2SA218..227
2SA369	Ge-PNP	AM-Pre/Mix/Osc, 20V, 10mA, 50MHz	2a	Mit	AF124..126, AF200, 2SA218..227
2SA37	Ge-PNP	HF, 18V, Ueb=12V, 5mA, 7MHz	2a	Tos	(AF124..127, AF200)
2SA370	Ge-PNP	HF, 75V, 50mA, 40MHz	2ao	Mit	AF118, SFT162, 2SA358
2SA371	Ge-PNP	Sw, 20V, Ueb=12V, 15mA, 0,08W, 10,5MHz	2a	Mit	ASY26..27, ASY48
2SA372	Ge-PNP	Fast-Sw, 15V, 0,2A, 0,1W, >350MHz, 6/45nS	2a	Tos	-
2SA373(A)	Ge-PNP	VHF-Dr, 25V, 0,15A, 0,25W, 400MHz	2a	Hit	-
2SA374	Ge-PNP	VHF-Dr, 34V, 0,3A, 300MHz	2a	Mat	-
2SA375	Ge-PNP	HF-Osc/Dr, Sw, 30V, 0,1A, 0,08W, 40MHz	2a	Mit	(ASY26..27, ASY48)
2SA376	Ge-PNP	FM, 22V, 10mA	5g	Son	AF124..125, AF106, AF109R, 2SA342
2SA377	Ge-PNP	VHF, 20V, 5mA, 200MHz	5g	Mat	AF109R, AF139, AF239(S)
2SA378	Ge-PNP	VHF, 20V, 5mA, 250MHz	5g	Mat	AF109R, AF139, AF239(S)
2SA379	Ge-PNP	VHF, 20V, 5mA, 300MHz	5g	Mat	AF109R, AF139, AF239(S)
2SA38	Ge-PNP	AM-IF, 18V, Ueb=12V, 5mA, 10MHz	2a	Tos	(AF124..127, AF200)
2SA380	Ge-PNP	AM-Mix/IF, 25V, 10mA, 60MHz	2a	old	AF124..126, AF200, 2SA218..227
2SA381	Ge-PNP	AM-Osc, 25V, 10mA, 35MHz	2a	old	AF124..126, AF200, 2SA218..227
2SA382	Ge-PNP	AM-Mix, 25V, 10mA, 30MHz	2a	old	AF124..126, AF200, 2SA218..227

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2SA383	Ge-PNP	AM-Pre/Mix, 25V, 10mA, 25MHz	2a	old	AF124..126, AF200, 2SA218..227
2SA384	Ge-PNP	AM-Pre/Mix/IF, 25V, 10mA, 40MHz	2a	old	AF124..126, AF200, 2SA218..227
2SA385	Ge-PNP	HF/Sw, 16V, Ueb=10V, 10mA, 10MHz	2a	Mat	ASY26..27, (AF124..127, AF200)
2SA386	Ge-PNP	VHF-Dr/Osc, 32V, 0,3A, 350MHz	2a	Mat	-
2SA387	Ge-PNP	AM-IF, 10V, 15mA	2a	Sanyo	AF124..127, AF200, 2SA218..227
2SA389	Ge-PNP	UHF, 20V, 10mA, 600MHz	5g	Hit	AF139, AF239(S)
2SA39	Ge-PNP	AM-IF, 18V, Ueb=12V, 5mA, 5,5MHz	2a	Tos	(AF124..127, AF200)
2SA390	Ge-PNP	UHF, 20V, 10mA, 700MHz	5g	Hit	AF139, AF239(S)
2SA391	Ge-PNP	HF, 18V, Ueb=12V, 0,2A, 0,15W, 7MHz	2a	Oki	ASY26..27
2SA392	Ge-PNP	HF, 18V, Ueb=12V, 0,2A, 0,15W, 11MHz	2a	Oki	ASY26..27
2SA393	Ge-PNP	HF, 18V, Ueb=12V, 0,2A, 0,15W, 16MHz	2a	Oki	ASY26..27
2SA393A	Ge-PNP	=2SA393:30V	2a	Oki	ASY26
2SA394	Ge-PNP	HF, 18V, Ueb=12V, 0,2A, 0,15W, 22MHz	2a	Oki	ASY26..27
2SA395	Ge-PNP	HF, 18V, Ueb=12V, 0,2A, 0,15W, 29MHz	2a	Oki	ASY26..27
2SA396	Ge-PNP	HF, 15V, Ueb=15V, 0,2A, 0,2W, 6MHz	2a	Oki	ASY26..27
2SA397	Ge-PNP	HF, 23V, Ueb=15V, 0,2A, 0,2W, 8MHz	2a	Oki	ASY26..27
2SA398	Ge-PNP	HF, 30V, Ueb=20V, 0,2A, 0,2W, 10MHz	2a	Oki	ASY26
2SA399	Ge-PNP	HF, 30V, Ueb=20V, 0,2A, 0,2W, 12MHz	2a	Oki	ASY26
2SA40	Ge-PNP	Sw, 25V, Ueb=12V, 0,05A, 5MHz	2a	Fui	ASY26..27, ASY48
2SA400	Ge-PNP	HF-Pre/Mix//Osc., 20V, 10mA, 70MHz	4g	Fui	AF124..126, AF200, 2SA218..227
2SA401	Ge-PNP	HF, 30V, 40mA, 230MHz	4g	Hit	AF121(S), AF202(S)
2SA402	Si-PNP	GenP, 35V, 0,1A, 0,25W, 200MHz	2a	Say, Tos	BC213, BC258, BC308, BC558..
2SA403	Ge-PNP	FM/VHF, 20V, 5mA, 280MHz	2a	Nec	AF109R, AF139, AF239(S)
2SA404	Ge-PNP	FM/VHF, 20V, 5mA, 400MHz	5g	Nec	AF109R, AF139, AF239(S)
2SA405	Ge-PNP	Sw, 15V, 0,05A, 0,15W, 50/110nS	2a	Nec	ASZ21, 2N2955..2957
2SA406	Ge-PNP	Sw, 30V, Ueb=20V, 0,2A, 0,2W, 9MHz	2a&	Nec	ASY26, ASY48
2SA407	Ge-PNP	Sw, 30V, Ueb=20V, 0,2A, 0,2W, 14MHz	2a&	Nec	ASY26, ASY48
2SA408	Ge-PNP	Sw, 15V, Ueb=15V, 0,05A, 0,05W, 50MHz	2a	Fui	ASZ21, 2N2955..2957
2SA409	Ge-PNP	Sw, 15V, Ueb=15V, 0,05A, 0,05W, 80MHz	2a	Fui	ASZ21, 2N2955..2957
2SA41(H)	Ge-PNP	HF, 35V, Ueb=20V, 40mA, 6MHz	2ao	Hit	(ASY26..27, ASY48)
2SA410	Ge-PNP	Fast-Sw, 12V, 0,15A, 0,15W, 25/90nS	2a$	Nec	ASZ21, 2N2955..2957
2SA411	Ge-PNP	Fast-Sw, 15V, 0,15A, 0,15W, 25/75nS	2a$	Nec	ASZ21, 2N2955..2957
2SA412	Ge-PNP	HF/Sw, 13V, 0,1A, 0,15W, 40MHz	2a	Hit	AFY18, 2N3323..3325
2SA413	Ge-PNP	Fast-Sw, 20V, 0,03A, 0,1W, 50/80nS	2a	Mat	ASZ21, 2N2635, 2N2955..2957
2SA414	Ge-PNP	Sw, 30V, Ueb=20V, 0,2A, 0,15W, 320/1300nS	2a	Mat	ASY26, ASY48
2SA415	Ge-PNP	Sw, 25V, Ueb=20V, 0,2A, 0,15W, 265/1300nS	2a	Mat	ASY26..27, ASY48
2SA416	Ge-PNP	Sw, Pow, 70V, 0,7A, 6W, 350/800MHz	23a$	Mat	(AUY10)
2SA417	Ge-PNP	Sw, 15V, 0,2A, 0,15W, <70/100nS	2a$	Nec	2N2955..2957
2SA419	Ge-PNP	VHF, 20V, 5mA, >350MHz	5g	Sanyo	AF139, AF239(S)
2SA42(H)	Ge-PNP	HF, 45V, Ueb=20V, 40mA, 6MHz	2ao	Hit	(ASY26..27, ASY48)
2SA420	Ge-PNP	VHF, 20V, 5mA, >300MHz	5g	Sanyo	AF139, AF239(S)
2SA421	Ge-PNP	UHF, 20V, 5mA, 680MHz	5g	Sanyo	AF139, AF239(S)
2SA422	Ge-PNP	UHF, 20V, 5mA, 880MHz	5g	Sanyo	AF139, AF239(S)
2SA423	Ge-PNP	UHF, 20V, 5mA	5g	Sanyo	AF139, AF239(S)
2SA424	Ge-PNP	UHF, 20V, 5mA	5g	Sanyo	AF139, AF239(S)
2SA425	Ge-PNP	VHF, 30V, 30mA, 350MHz	5g	old	AF139, AF239(S)
2SA426	Ge-PNP	VHF, 30V, 30mA, 500MHz	5g	old	AF139, AF239(S)
2SA427	Ge-PNP	HF, 20V, 15mA, 45MHz	4g	Sanyo	AF124..126, AF200, 2SA340..342
2SA428	Ge-PNP	HF, 20V, 15mA, 50MHz	4g	Sanyo	AF124..126, AF200, 2SA340..342
2SA429(G,GTM)	Si-PNP	Nix, Vid, 150V, 0,03A, 100MHz	7c	Tos	BF398, BF421, BF423, BF435..437..
2SA43	Ge-PNP	FM-IF, 35V, 10mA, 40MHz	4g	Fui	AF124..126, AF200, 2SA103..104
2SA430	Ge-PNP	UHF, 20V, 5mA, >450MHz	5g	Tos	AF139, AF239(S)
2SA431(A)	Ge-PNP	VHF, 20V, 5mA, 500MHz	5g	Tos	AF139, AF239(S)
2SA432(A)	Ge-PNP	VHF, 20V, 5mA, 450MHz	5g	Tos	AF139, AF239(S)
2SA433	Ge-PNP	FM/IF, 18V, 5mA, 34MHz	4g	Tos	AF124..126, AF200, 2SA218..227
2SA434	Ge-PNP	FM/VHF, 20V, 10mA, 880MHz	1g	Hit	AF109R, AF139, AF239(S)
2SA435	Ge-PNP	FM/VHF, 20V, 10mA, 330MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA436	Ge-PNP	FM/VHF, 20V, 10mA, 400MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA437	Ge-PNP	FM/VHF, 20V, 10mA, 400MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA438	Ge-PNP	FM/VHF, 20V, 10mA, 520MHz	5g	Hit	AF109R, AF139, AF239(S)
2SA44	Ge-PNP	HF/AF, 15V, Ueb=10V, 10mA, 15MHz	1a	Mat	(AF124..127, AF200, 2SA201..202)
2SA440(A)	Ge-PNP	FM/VHF, 20V, 5mA, 350MHz	5g	Sanyo	AF109R, AF139, AF239(S)
2SA441	Ge-PNP	FM/VHF, 20V, 10mA, 500MHz	2a	Sanyo	AF109R, AF139, AF239(S)
2SA443	Ge-PNP	Dual, Chopper, 21V, 15mA, 25MHz	-	Hit	-

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2SA444	Ge-PNP+Di	Sw+integr.Diode,16V,12mA,12MHz	-	Hit	-
2SA445	Ge-PNP	Dual,16V,15mA,10MHz	-	Hit	-
2SA446	Ge-PNP	Fast-Sw,15V,0,2A,0,2W,20/145nS	2a$	Tos	2N2955..2957
2SA447	Ge-PNP	VHF/UHF,25V,15mA,650MHz	5g	Mat	AF139,AF239(S)
2SA448	Ge-PNP	UHF,15V,5mA,1700MHz	5g	Son	2N5043,(AF239S)
2SA449	Ge-PNP	Fast-Sw,10V,0,1A,0,15W,<80/120nS	2a	Hit	ASZ21,2N2955..2957
2SA45	Ge-PNP	AM-IF,18V,Ueb=12V,5mA	2a	Tos	(AF124..127,AF200,2SA201..203)
2SA450(H)	Ge-PNP	Fast-Sw,12V,0,1A,0,15W,<60/95nS	2a	Hit	ASZ21,2N2955..2957
2SA451(H)	Ge-PNP	Fast-Sw,12V,0,1A,0,15W,<60/110nS	2a	Hit	ASZ21,2N2955..2957
2SA452(H)	Ge-PNP	Fast-Sw,12V,0,1A,0,15W,<60/120nS	2a	Hit	ASZ21,2N2955..2957
2SA453	Ge-PNP	FM/VHF,22V,10mA,630MHz	5g	Son	AF109R,AF139,AF239(S)
2SA454	Ge-PNP	FM/VHF,22V,10mA,630MHz	5g	Son	AF109R,AF139,AF239(S)
2SA455	Ge-PNP	FM/VHF,22V,10mA,630MHz	5g	Son	AF109R,AF139,AF239(S)
2SA456	Ge-PNP	FM/VHF,22V,10mA,630MHz	5g	Son	AF109R,AF139,AF239(S)
2SA457	Ge-PNP	AM-Pre/Mix/Osc,18V,20mA,45MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA458	Ge-PNP	Sw,25V,0,2A,0,15W,<1000/700nS,B=60	2a	Mit	ASY26..27,ASY48
2SA459	Ge-PNP	=2SA458:B=120	2a	Mit	ASY26..27,ASY48
2SA46	Ge-PNP	HF/AF,12V,25mA,10MHz	2a	Fui	AF124..127,AF200,2SA201..202
2SA460	Ge-PNP	FM/VHF,20V,10mA,400MHz	4g	Mit	AF109R,AF139,AF239(S)
2SA461	Ge-PNP	FM/VHF,20V,10mA,400MHz	4g	Mit	AF109R,AF139,AF239(S)
2SA462	Ge-PNP	FM/VHF,20V,10mA,400MHz	4g	Mit	AF109R,AF139,AF239(S)
2SA463	Ge-PNP	FM/VHF,20V,10mA,300MHz	4g	Mit	AF109R,AF139,AF239(S)
2SA464	Ge-PNP	VHF/UHF,15V,10mA,850MHz	4g	Mit	AF139,AF239(S)
2SA465	Ge-PNP	UHF,20V,5mA,600MHz	5g	Mat	AF139,AF239(S)
2SA466	Ge-PNP	HF,18V,10mA,15MHz	2a	Tos	AF124..127,AF200,2SA218..227
2SA467(G,GTM)	Si-PNP	GenP,40V,0,4A,0,3W,200MHz	7c	Tos	BC327,BC636,BC638,BC640..
2SA468	Ge-PNP	AM-Pre/Mix/Osc,18V,10mA,45MHz	2a	Tos	AF124..126,AF200,2SA220..227
2SA469	Ge-PNP	AM-Pre/Mix/Osc,18V,10mA,30MHz	2a	Tos	AF124..126,AF200,2SA220..227
2SA47	Ge-PNP	HF/AF,12V,25mA,6MHz	2a	Fui	AF124..127,AF200,2SA201..203
2SA470	Ge-PNP	AM-Pre/Mix/Osc,18V,10mA,35MHz	2a	Tos	AF124..126,AF200,2SA220..227
2SA471	Ge-PNP	FM-IF,18V,10mA,35MHz	2a	Tos	AF124..126,AF200,2SA220..227
2SA472	Ge-PNP	AM-Pre/Mix/Osc/IF,18V,10mA,35MHz	2a	Tos	AF124..126,AF200,2SA220..227
2SA473	Si-PNP	AF,Sw-Pow,30V,3A,10W,100MHz	17j$	Mic,Tos	2SA1012,2SB1273,2SA1288..1289
2SA474	Ge-PNP	HF,50V,0,05A,0,12W,70MHz	2a	Tos	(AF121(S),AF202(S))
2SA475	Ge-PNP	HF,20V,0,05A,0,12W,30MHz	2a	Tos	(AF121(S),AF202(S))
2SA476	Ge-PNP	HF,18V,10mA,130MHz	2a	Tos	AF106,AF109R,2SA345..349
2SA477	Ge-PNP	FM-IF,18V,10mA,45MHz	2a	Tos	AF124..126,AF200,2SA218..227
2SA478	Ge-PNP	Sw,40V,0,4A,0,125W,>25MHz,-/335nS	2a	Tos	2N705,2N960..967,2N2955..2957
2SA479	Ge-PNP	Sw,40V,0,2A,0,125W,>25MHz,-/<370nS	2a	Tos	2N705,2N960..967,2N2955..2957
2SA48	Ge-PNP	AM-Pre/Mix/Osc,18V,Ueb=12V,5mA	2a	Tos	(AF124..127,AF200,2SA201..203)
2SA480	Si-PNP	AM/FM,30V,100mA,70MHz	2a	Son	BF324,BF440..441,BF450..451..
2SA482	Si-PNP	GenP,40V,0,6A,0,6W,70MHz	2a$	Tos	BC160..161,BC303..304,2N2904..05..
2SA483	Si-PNP	Sw,Pow,TV-VD,150V,1,5A,20W,10MHz	22a$	Tos	2SA839,2SA940,2SB628(A),2SB861..
2SA484	Si-PNP	GenP,110V,1,5A,0,8W,20MHz	2a$	Tos	BCX60,2N3634..3637
2SA485	Si-PNP	=2SA484:80V	2a$	Tos	BCX60,BSV17,BSS17..18,2N5322..23
2SA486	Si-PNP	=2SA484:50V	2a$	Tos	BCX60,BSV16..17,2N5322..5323..
2SA489	Si-PNP	AF,Sw-Pow,70V,4A,30W,>3MHz	17j$	Mic,Tos	BD242B,BD244A,BD538,BD5408,BD952..
2SA49	Ge-PNP	AM-IF,18V,Ueb=12V,5mA,9MHz	2a	Tos	(AF124..127,AF200,2SA201..203)
2SA490	Si-PNP	AF,Sw*Pow,50V,3A,25W,>3MHz	17j$	Mic,Tos	BD242B,BD244,BD536,BD936..
2SA493(GTM)	Si-PNP	GenP,LN,50V,0,05A,0,2W,80MHz	7c	Toshiba	BC214,BC416,BC560,2SA1136..1137
2SA494	Si-PNP	GenP,LN,35V,0,03A,0,2W,200MHz	7c	Toshiba	BC214,BC259,BC309,BC559,2SA1137+
2SA495(GTM)	Si-PNP	GenP,35V,0,1A,0,2W,200MHz	7c	Toshiba	BC213,BC257,BC307,BC557,2SB725..
2SA496	Si-PNP	GenP,Pow,40V,1A,5W,100MHz	14h$	Toshiba	BD136,BD227,BD238,BD376,2SB1009
2SA497	Si-PNP	GenP,80V,0,8A,0,6W,70MHz	2a$	Toshiba	BC303,BCX60,BSV17,2N3634..35..
2SA498	Si-PNP	=2SA497:50V	2a$	Toshiba	BC161,BC303..304,BCX60,BSV16..
2SA499(M)	Si-PNP	HF/Sw,50V,0,1A,0,25W,250MHz	2a$	Toshiba	BC212,BC257,BC307,BC557..
2SA50	Ge-PNP	Sw,18V,Ueb=12V,24mA,14MHz	2a	Toshiba	ASY26..27,ASY48
2SA500(M)	Si-PNP	=2SA499:30V	2a$	Toshiba	BC213,BC258,BC308,BC558,2N3906..
2SA500D	Si-PNP	=2SA499:35V	2a$	-	BC213,BC258,BC308,BC558..
2SA501	Si-PNP	GenP,40V,0,2A,0,75W,200MHz	2a$	Toshiba	BC160..161,BC303..304,2N2303..
2SA502	Si-PNP	Nix,90V,0,1A,0,3W,>50MHz	7c	Tos	BF397..398,BSS68,2SA970,2SA1285..
2SA503(M)	Si-PNP	GenP,100V,0,6A,0,8W,60/530nS	2a$	Tos,Mic	BCX60,BSW40
2SA504(M)	Si-PNP	=2SA503:80V	2a$	-	BC303,BCX60,BSW40,2N4036..
2SA505	Si-PNP	GenP,Pow,60V,1A,5W,100MHz	14h	Tos	BD138,BD229,BD238,BD378,2SB744(A)..

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2SA506	Ge-PNP	VHF,20V,5mA,300MHz	5g	Tos	AF109R,AF139,AF239(S)
2SA507	Ge-PNP	VHF,20V,5mA,250MHz	5g	Tos	AF109R,AF139,AF239(S)
2SA508	Ge-PNP	VHF,20V,5mA,200MHz	5g	Tos	AF109R,AF139,AF239(S)
2SA509	Si-PNP	GenP,35V,0,5A,0,6W,140MHz	9b	Toshiba	BC327,BC636,BC638,2SA1515..
2SA509GTM	Si-PNP	=2SA509:	7c	-	→2SA509
2SA51	Ge-PNP	AM-Pre/Mix/Osc,18V,Ueb=12V,5mA,14MHz	2a	Tos	(AF124..127,AF200,2SA202)
2SA510(M)	Si-PNP	AF/HF/Sw,120V,1,5A,0,8W,60MHz	2a$	Tos	2N3634..3637
2SA511	Si-PNP	=2SA510:90V	2a$	Tos	BCX60,BSS17,BSV17,2N5322
2SA512(M)	Si-PNP	=2SA510:80V	2a$	Tos	BCX60,BSS17..18,2N5322..5323..
2SA513	Si-PNP	=2SA510:60V	2a$	Tos	BC161,BCX60,BSV16,2N5322..23..
2SA516(N)	Si-PNP	GenP,80V,1,5A,0,8W,50MHz	2a$	Tos	BCX60,BSS17..18,2N5322..5323..
2SA516A	Si-PNP	=2SA516:120V	2a$	-	2N3634..3637
2SA517	Ge-PNP	HF,18V,10mA,60MHz	2a	Tos	AF124..126,AF200,2SA218..227
2SA518	Ge-PNP	HF,18V,10mA,45MHz	2a	Tos	AF124..126,AF200,2SA218..227
2SA52	Ge-PNP	AM-IF,18V,Ueb=12V,5mA,9MHz	2a	Tos	(AF124..127,AF200,2SA201..202)
2SA522(N)	Si-PNP	GenP,25V,0,1A,0,25W,200MHz	2a$	Fui,Tos	BC213,BC258,BC308,BC558..
2SA522A	Si-PNP	=2SA522:50V	2a$	-	BC212,BC257,BC307,BC557..
2SA523(N)	Si-PNP	GenP,40V,0,3A,0,65W,200MHz	2a$	Fui	BC160..161,BC303..304,2N2904..05..
2SA523A	Si-PNP	=2SA523:60V	2a$	-	BC161,BC303..304,2N2904..2905..
2SA524	Si-PNP	GenP,25V,0,1A,0,35W,250MHz	2a$	Fui	BC213,BC258,BC308,BC558..
2SA525	Ge-PNP	FM/VHF,20V,5mA,250MHz	5g	Tos	AF109R,AF139,AF239(S)
2SA526	Si-PNP	GenP,50V,1A,0,5W	2a$	Son	BC161,BSV16..17,2N2904..2905..
2SA527	Si-PNP	HF/Sw,50V,2A,5W,80MHz	43g$	Son	(BD510,BD518,BD526,BD376,..)
2SA528	Si-PNP	HF/Sw,50V,2A,5W,80MHz	43g$	Son	(BD510,BD518,BD526,BD376,..)
2SA529	Si-PNP	HF/Sw,50V,1A,5W(Tc=25°)	2a$	Son	BC161,BSV16..17,2N2904..2905..
2SA53	Ge-PNP	AM-IF,18V,Ueb=12V,5mA,7MHz	2a	Tos	(AF124..127,AF200,2SA201..202)
2SA530(H)	Si-PNP	Sw,50V,0,1A,0,2W,90/160nS	2a$	Hit	BC557,BSW24,2N2906..07,2N3250..51..
2SA531(H)	Si-PNP	60V,0,4A,0,6W	2a$	Hit	-
2SA532	Si-PNP	GenP,50V,0,2A,0,5W,90MHz	2a&	Say,Mic	BC161,BSV16..17,2N2904..2905..
2SA532-3	Si-PNP	=2SA532:75V	2a&	-	BC161,BSV16..17,2N2904..2905..
2SA532-4	Si-PNP	=2SA532:50V	2a&	-	BC161,BSV16..17,2N2904..2905..
2SA535	Si-PNP	GenP,75V,0,7A,0,5W,80MHz	2a$	Sanyo	BC303,BSV17,BSW40,2N3634..37..
2SA536	Si-PNP	=2SA535:50V	2a$	Sanyo	BC161,BC303..304,2N2904..2905..
2SA537(H)	Si-PNP	Sw,60V,0,7A,0,75W,150MHz,<50/350nS	2a$	Hit	BSW40,2N4030..4033,2N4036..4037..
2SA537A	Si-PNP	=2SA536:100V	2a$	-	BSW40
2SA538	Ge-PNP	HF/Sw,25V,Ueb=12V,0,05A,0,12W,8MHz	2a	Tos	ASY26..27,ASY48
2SA539(S)	Si-PNP	GenP,60V,0,2A,0,25W,160MHz	7c	Mic,Nec	BC212,BC256,BC266,BC556..
2SA54	Ge-PNP	VHF,20V,5mA,400MHz	5g	Nec	AF109R,AF139,AF239(S)
2SA542	Si-PNP	GenP,30V,0,05A,0,15W,>30MHz	24b	Nec	(BC213,BC258,BC308,BC558,..)
2SA543	Si-PNP	=2SA542:ra	24b	Nec	(BC214,BC259,BC309,BC559,..)
2SA544	Si-PNP	GenP,Sw,60V,0,2A,0,75W,<50/250nS	2a$	Nec,Mic	BC161,BC303..304,2N2904..2905..
2SA545	Si-PNP	GenP,70V,0,2A,0,4W,180MHz	7co	Nec,Mic	BC640,2SB647,2SB910,2SB1041..
2SA546(Z)	Si-PNP	GenP,70V,1A,0,75W,80MHz	2a$	Mat	BCX60,BSS17..18,2N5322..5323..
2SA546A	Si-PNP	=2SA546:90V	2a$	-	BCX60,BSS17,2N5322
2SA547(Z)	Si-PNP	=2SA546:10W	43a$	Mat	(BD520,BD528,BD530,BD378)
2SA547A	Si-PNP	=2SA546:90V,10W	43a$	-	(BD530,BD380)
2SA548(H)	Si-PNP	HF/Sw,50V,0,1A,0,2W,90/160nS	2a	Hit	BC557,BSW24,2N2906..07,2N3250..51..
2SA549(H)	Si-PNP	Mix,Sw,70V,0,1A,0,2W,>40MHz	2a	Hit	BC556,BF397..398,BSS68,2SA970..
2SA549A	Si-PNP	=2SA549:150V,0,05A	2a	-	BF398,BF435,2SA1019,2SA1285A..
2SA55	Ge-PNP	HF,15V,Ueb=10V,10mA,6MHz	1a	Mat	(AF124..127,AF200,2SA201..203)
2SA550(Z)	Si-PNP	GenP,25V,0,1A,0,3W,120MHz	2a$	Mat,Mic	BC213,BC258,BC308,BC558,2SA1137+
2SA550A	Si-PNP	=2SA550:45V	2a$	-	BC212,BC257,BC307,BC557,2SA1137+
2SA551	Si-PNP	GenP,70V,0,4A,0,6W,80MHz	-	Sanyo	BC303,BC640,BSV17,2SB647..
2SA552	Si-PNP	HF/Sw,60V,0,2A,0,75W,<100/300nS	2a$	Nec	BSW23,2N2904..2905,2N3072..3073..
2SA553	Si-PNP	GenP,40V,0,3A,0,25W,200MHz	2a$	Fui	BC213,BC257,BC307,BC557..
2SA554	Si-PNP	GenP,25V,0,3A,0,25W,200MHz	2a$	Fui	BC213,BC258,BC308,BC558..
2SA554A	Si-PNP	=2SA554:40V	2a$	-	BC213,BC257,BC307,BC557..
2SA555	Si-PNP	GenP,50V,0,2A,0,2W,200MHz,-/195nS	7c	Fui	BC213,BC257,BC307,BC557..
2SA556	Si-PNP	GenP,20V,0,2A,0,2W,200MHz	(7b)	Fui	BC213,BC258,BC308,BC558..
2SA557	Si-PNP	GenP,20V,0,25A,0,3W,200MHz	8a	Fui	BC213,BC258,BC308,BC558..
2SA558	Si-PNP	Sw,40V,0,2A,0,35W,200MHz,-/115nS	2a$	Fui	BSW24,2N2906..2907,2N3905..3906..
2SA559	Si-PNP	Sw,20V,0,2A,0,35W,200MHz,-/115nS	2a$	-	BSW24,2N2906..2907,2N3905..3906..
2SA559A	Si-PNP	=2SA559:40V	2a$	-	BSW24,2N2906..2907,2N3905..3906..
2SA56	Ge-PNP	Fast-Sw,15V,50mA,300MHz,50/110nS	2a	Nec	ASZ21,2N2635,2N2955..2957

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2SA560(N)	Si-PNP	GenP,80V,0,8A,0,8W,150MHz	2a$	Fui,Tos	BC303,BCX60,BSV17,2N3634..37..
2SA561	Si-PNP	GenP,50V,0,15A,0,3W,70MHz	7c	Tos	BC327,BC638,BC640,2N2906..2907..
2SA562	Si-PNP	30V,0.5A,0.5W,200MHz	-		-
2SA562(TM)	Si-PNP	GenP,30V,0,4A,0,3W,70MHz	7c	Tos	BC327..328,BC636,2SA1515,2SB910,..
2SA564(Z)	Si-PNP	GenP,25V,0,1A,0,4W,200MHz	7c	Mat,Mic	BC213,BC258,BC308,BC558..
2SA564A(Z)	Si-PNP	=2SA564:45V	7c	-	BC212,BC257,BC307,BC557..
2SA565(K)	Si-PNP	GenP,50V,0,5A,0,3W,60MHz	2a	Hit	BC327,BC638,BC640,2N2906..2907..
2SA566	Si-PNP	100V,0.7A,10W,100MHz	-		-
2SA566(H)	Si-PNP	AF/HF/Sw-Pow,100V,0,7A,10W,100MHz	22a$	Hit	2N5344,2SA913(A),2SA985(A),2SA1111,..
2SA567	Si-PNP	GenP,30V,0,1A,0,2W,70MHz	2a	Hit	BC213,BC258,BC308,BC558..
2SA568	Si-PNP	GenP,35V,0,25A,0,2W,150MHz	7b	Mit	BC327,BC636,2SA953,2SA1515,..
2SA569	Si-PNP	=2SA568:50V	7b	Mit	BC638,BC640,2SB647,2SB910,2SB1041+
2SA57	Ge-PNP	HF,18V,5mA,85MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA570	Si-PNP	=2SA568:65V	7b	Mit	BC638,BC640,2SB647,2SB910,2B1041..
2SA571	Si-PNP	Sw,60V,1A,0,8W,300MHz,25/110nS	2a$	Nec	BSW40,2N2904..2905,2N4030..4033..
2SA573	Si-PNP	GenP,30V,0,1A,0,3W,150MHz	7c	Njr	BC213,BC258,BC308,BC558..
2SA574	Si-PNP	=2SA573:60V	7c	Njr	BC212,BC256,BC266,BC556..
2SA575	Si-PNP	=2SA573:90V	7c	Njr	2SA970,2SA1049,2SA1285(A),2SA1136,..
2SA576	Si-PNP	GenP,30V,0,2A,0,6W,200MHz	8a	Njr	BC327..328,BC636,2SA953,2SA1515,..
2SA577	Si-PNP	GenP,60V,0,4A,0,6W,200MHz	8a	Njr	BC327A,BC638,BC640,2N2906..07..
2SA578	Si-PNP	General purpose,low noise,50V,0,03A,0,3W,180MHz	2a$	Nec	BC214,BC416,BC560,2SA1136..1137,..
2SA579	Si-PNP	=2SA578	2a$	Nec	→2SA578
2SA58	Ge-PNP	HF,18V,5mA,75MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA580	Si-PNP	GenP,60V,0,6A,0,8W,100MHz	2a$	Fui	BC161,BC303..304,2N2904..2905..
2SA581	Si-PNP	=2SA580:100V	2a$	Fui	BC303,BCX60,BSW40,2N3634..3637..
2SA59	Ge-PNP	HF,18V,5mA,65MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA594(M,N)	Si-PNP	HF/Sw,60V,0,2A,0,7SW,200MHz	2a$	Nec,Tos	BSW23,2N3072..3073,2N2904..2905..
2SA597(N)	Si-PNP	HF/Sw,50V,1A,400MHz	2a$	Tos	BSW40,2N2904..2905,2N4030..4033..
2SA60	Ge-PNP	HF,18V,5mA,55MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA603	Si-PNP	GenP,60V,0,2A,0,3W,250MHz	2a$	Nec	BC212,BC556,BSW24,2N2906..2907..
2SA604	Si-PNP	Nix,120V,0,03A,0,3W,170MHz	2a$	Nec	BF398,BF423,BF435..437,2SA1370..72
2SA605	Si-PNP	Nix,180V,0,05A,0,3W,100MHz	2a$	Nec	BF435..437,2SA1370..1372
2SA606(S)	Si-PNP	GenP,100V,0,7A,0,7W,100MHz	2a$	Nec,Mic	BCX60,BSW40,2N3634..3637
2SA607(S)	Si-PNP	=2SA606:	43a$	Nec	(BD380,BD530,2SA1014,2SB874..875)
2SA608	Si-PNP	GenP,30V,0,1A,0,1W,180MHz	7c	Sanyo	BC213,BC258,BC308,BC558..
2SA608K,KNP	Si-PNP	=2SA608:55V,0,25W	7c	-	BC212,BC257,BC307,BC557..
2SA608NP	Si-PNP	=2SA608:40V,0,25W	7c	-	BC212,BC257,BC307,BC557..
2SA608SP	Si-PNP	=2SA608:40V,0,2W	41c	-	BC212,BC257,BC307,BC557..
2SA609	Si-PNP	GenP,30V,0,1A,0,1W,80MHz	7c	Sanyo	BC213,BC258,BC308,BC558..
2SA609NP	Si-PNP	=2SA609:0,25W	7c	-	BC213,BC258,BC308,BC558..
2SA609SP	Si-PNP	=2SA609:0,2W	41c	-	BC213,BC258,BC308,BC558..
2SA61	Ge-PNP	HF,20V,10mA,70MHz	2a	Mat	AF124..127,AF200,2SA218..227
2SA610	Si-PNP	GenP,30V,0,1A,0,15W,170MHz	7c	Njr	BC213,BC258,BC308,BC558..
2SA611	Si-PNP	=2SA610:60V	7c	Njr	BC212,BC256,BC266,BC556..
2SA612	Si-PNP	GenP,90V,0,05A,0,2W,150MHz	?2b	Njr	BF397..398,2SA893,2SA970,2SB715..
2SA613	Si-PNP	AF,Sw-Pow,60V,1A,15W,30MHz	22a$	Nec	BD240A,2SA748,2SA1111..1112..
2SA614	Si-PNP	AF,Sw-Pow,80V,1A,15W,30MHz	22a$	Nec	BD240B,2SA913,2SA1111..1112..
2SA615	Si-PNP	AF,Sw-Pow,70V,3A,25W	22a$	Nec	BD242A,BD538,BD938,BDX14..
2SA616	Si-PNP	AF,Sw-Pow,80V,3A,25W,15MHz	22a$	Nec	BD242B,BD538,BD938,BDX14..
2SA617(K)	Si-PNP	Nix,150V,0,05A,0,2W,60MHz	2a	Hit	BF398,BF423,BF435..437,2SA1370..
2SA618(K)	Si-PNP	=2SA617:180V	2a	Hit	BF423,BF435..437,2SA1370..1372..
2SA620	Si-PNP	GenP,LN,30V,0,05A,0,2W,120MHz	?2b	Njr	BC214,BC259,BC309,BC559..
2SA621	Si-PNP	GenP,60V,0,2A,0,4W,200MHz	2a	Njr	BC161,BC303..304,BSW23,2SA606..
2SA622	Si-PNP-Darl	Sw,30V,0,3A,0,15W,B=40000	7c	Njr	BC516,BC876,BSR60..62,MPSA75..
2SA623	Si-PNP	AF,Sw-Pow,35V,1,5A,7W,70MHz	13I$	Mitsubishi	BD238
2SA624	Si-PNP	=2SA623:50V	13I$	Mit	BD238
2SA625	Si-PNP	GenP,100V,0,5A,0,7W,100MHz	2a$	Fui	BC461,BCX60,2SA606
2SA626	Si-PNP	AF,Sw-Pow,80V,5A,60W,15MHz	23a$	Nec	BD246B,BD314,BDW52C,2N6226,2SB775..776..
2SA627	Si-PNP	=2SA626:100V	23a$	Nec	BD246C,BD318,BDW52C,2N6226,2SB775..776..
2SA628	Si-PNP	GenP,30V,0,1A,0,15W,100MHz	7b	Mit	BC213,BC258,BC308,BC558..
2SA628A	Si-PNP	=2SA628:60V	7b	-	BC212,BC256,BC266,BC556..
2SA629	Si-PNP	GenP,LN,30V,0,03A,0,15W,100MHz	7b	Mit	BC213,BC259,BC309,BC559..
2SA631	Ge-PNP	HF,40V,0,05A,>40MHz	2a	Hit	(AF121(S);AF202(S),AFY18)
2SA633	Si-PNP	AF,Sw-Pow,30V,2A,10W,60MHz	13J$	NEC	2SA699,BD238

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2SA634	Si-PNP	AF,Sw-Pow,40V,3A,10W,55MHz	13j$	NEC	BD238
2SA635	Si-PNP	AF,Sw-Pow,60V,1A,10W,50MHz	13j$	NEC	2SA887,BD238
2SA636	Si-PNP	AF,Sw-Pow,70/45V,3A,10W,45MHz	13j$	NEC	BD238
2SA636A	Si-PNP	=2SA636:70/60V	13j$	-	(BD620)
2SA637	Si-PNP	Nix,150V,0,05A,0,3W,150MHz	2a$	Mat,Mic	BF398,BF423,BF435..437,2SA1370..
2SA638(S)	Si-PNP	Nix,150V,0,05A,0,25W,130MHz	7c	Nec	BF398,BF423,BF435..437,2SA1370..
2SA639	Si-PNP	180V,50mA,0.25W	-		-
2SA639(S)	Si-PNP	=2SA638:180V	7c	Nec	BF423,BF435..437,2SA1370..1372..
2SA64	Ge-PNP	Sw,16V,0,04A,15MHz,-/1850nS	2a	Fui	ASY26..27,ASY48
2SA640	Si-PNP	GenP,LN,50V,0,03A,0,25W,100MHz	7c	Nec	BC214,BC416,BC560,2SA1136..1137,..
2SA641	Si-PNP	GenP,50V,0,03A,0,25W,100MHz	7c	Nec	BC212,BC256,BC266,BC556..
2SA642	Si-PNP	GenP,30V,0,2A,0,25W,200MHz	7c	Nec,Mic	BC327..328,BC636,BC638,BC640..
2SA643	Si-PNP	GenP,40V,0,5A,0,5W,180MHz	7co	Nec,Mic	BC327,BC636,BC638,BC640..
2SA645	Si-PNP	AF,Sw-Pow,70,0,8A,7W,>35MHz	13l$	Mitsubishi	MJE182
2SA646	Si-PNP	=2SA645:90V	13l$	Mit	BD238
2SA647	Si-PNP	=2SA645:110V	13l$	Mit	BD238
2SA648	Si-PNP	AF,Sw-Pow,120V,7A,60W,10MHz	23a$	Nec	BD246D,2SB681,2SB695,2SB696,2SB816..
2SA649	Si-PNP	=2SA648:150V	23a$	Nec	BD246D,2SB681,2SB695,2SB696,2SB816..
2SA65	Ge-PNP	Sw,18V,Ueb=12V,0,2A,6MHz,-/240nS	2a	Tos	ASY26..27,ASY48,ASY76..77
2SA650	Si-PNP	AF,Sw-Pow,150V,10A,100W,10MHz	23a$	Nec	BD246D,2SA1386,2SB681,2SB817,2SB908..
2SA651	Si-PNP	AF,Sw-Pow,200V,10A,100W,10MHz	23a$	Nec	BD246F,2SA1116,2SA1294,2SB600,2SB645+
2SA652	Si-PNP	AF,Sw-Pow,150/100V,1A,15W,15MHz	22a$	Nec	BD240D,2SB608,2SB628(A),2SB861,2SB991
2SA653	Si-PNP	=2SA652:150/120V	22a$	Nec	BD240D,2SB608,2SB628(A),2SB861,2SB991
2SA653A	Si-PNP	=2SA652:150/140V	22a$	-	BD240E,2SB608,2SB628(A),2SB861,2SB991
2SA656(A)	Si-PNP	AF,Sw-Pow,130V,7A,50W,5MHz	23a$	Tos	BD246D,2N6231,2SB555,2SB681,2SB816..
2SA657(A)	Si-PNP	=2SA656:100V	23a$	Tos	BD318,BD246C,2SB688,2SB681..
2SA658(A)	Si-PNP	=2SA656:70V	23a$	Tos	BD316,BD246B,2SB688,2SB681..
2SA659(NP)	Si-PNP	GenP,50V,0,2A,0,3W,90MHz	7c	Say,Mic	BC212,BC257,BC307,BC557..
2SA66	Ge-PNP	Sw,18V,Ueb=12V,0,2A,10MHz,-/225nS	2a	Tos	ASY26..27,ASY48,ASY76..77
2SA661	Si-PNP	GenP,70V,0,2A,0,6W,100MHz	9b	Toshiba	BC212,BC256,BC266,BC556..
2SA663	Si-PNP	AF,Sw-Pow,100V,7A,60W,6MHz	23a$	Tos	BD318,BD246C,BDW52C,2N6229,2SB775..776..
2SA666	Si-PNP	GenP,LN,25V,0,05A,0,25W,130MHz	7c	Mat,Mic	BC214,BC259,BC309,BC559..
2SA666A	Si-PNP	=2SA666:45V	7c	-	BC214,BC416,BC560,2SA1136..37..
2SA668	Si-PNP	Sw,Vid,100V,0,1A,0,15W,100MHz	7b	Mit	BF398,BF435..437,BSS68,2SA1370..
2SA669	Si-PNP	Sw,Vid,160V,0,1A,0,15W,100MHz	7b	Mit	BF398,BF435..437,2SA1370..1372..
2SA67	Ge-PNP	Sw,18V,Ueb=12V,0,2A,14MHz	2a	Tos	ASY26..27,ASY48,ASY76..77
2SA670	Si-PNP	AF,Sw-Pow,50V,3A,25W,32MHz	17j$	Hit,Mic	BD242,BD536,BD936,TIP32B,2SA1288..
2SA671(K)	Si-PNP	AF,Sw-Pow,50V,3A,25W,32MHz	17j$	Hit	BD242,BD536,BD936,2SA1288..
2SA672	Si-PNP	GenP,LN,50V,0,2A,0,2W,80MHz	9b	Hitachi	BC214,BC416,BC560,2SA1136..37..
2SA673	Si-PNP	GenP,35V,0,5A,0,4W,50MHz	9b,7c	Hit	BC327..328,BC636,2SA1515,2SB910,..
2SA673A(AK)	Si-PNP	=2SA673:50V	9b,7c	Hit	BC327,BC636,2SA1683,2SB910,..
2SA675	Si-PNP	GenP,80V,0,1A,0,25W,170MHz	7c	Nec,Mic	BC556,2SA970,2SA1049,2SA1136
2SA677	Si-PNP	GenP,25V,0,2A,0,32W,140MHz	10b	Son	BC213,BC258,BC308,BC558..
2SA678	Si-PNP	=2SA677:50V	10b	Son	BC212,BC257,BC307,BC557..
2SA679	Si-PNP	AF,Sw-Pow,120V,12A,100W,6MHz	23a$	Tos	BD746D,MJ2955,2N6030..6031,2SB555..556..
2SA68	Ge-PNP	AM,20V,10mA,70MHz	1g	Mat	AF124..125,AF200,2SA218..227
2SA680	Si-PNP	=2SA679:100V	23a$	-	BD746C,BDW52C,2N6029..6031,2SB555..556..
2SA681	Si-PNP	AF,Sw-Pow,100V,1A,50MHz	14h$	Tos	BD140,BD231,BD380,2SB874..875..
2SA682	Si-PNP	AF,Sw-Pow,80V,0,75A,5W,100MHz	14h$	Tos	BD140,BD231,BD238,BD380,2SA1184..
2SA683(NC)	Si-PNP	GenP,30V,1A,1W,200MHz	7c(9mm)	Mat	2SA966,2SB978,2SB927,2SB1312..
2SA684	Si-PNP	60V,1A,1W,200MHz	-		-
2SA684(NC)	Si-PNP	=2SA683:60V	7c(9mm)	Mat	2SA1315,2SB764,2SB892,2SB1041
2SA685	Si-PNP	Nix,GenP,150V,0,05A,0,3W,100MHz	7c	Mat,Mic	BF398,BF423,BF435..437,2SA1370..
2SA69	Ge-PNP	AM,20V,10mA,70MHz	1g	Mat	AF124..125,AF200,2SA218..227
2SA695	Si-PNP	GenP,25V,0,7A,0,5W,150MHz	7b	Mit	BC327..328,BC636,BC638,2SB910,..
2SA696	Si-PNP	GenP,45V,0,3A,0,5W,130MHz	7b	Mit	BC327,BC636,BC638,MJE350,2SB910..
2SA697	Si-PNP	=2SA696:65V	7b	Mit	BC327A,BC638,BC640,2SB647..
2SA698	Si-PNP	AF,Sw-Pow,130V,0,8A,7W,<200/800nS	13l$	Mitsubishi	(2SA1195)
2SA699	Si-PNP	AF,Sw-Pow,40V,2A,10W,150MHz	13j$	Matsushita	2SA887,TIP30A
2SA699A	Si-PNP	=2SA699:50/40V	13j$	-	2SA887,TIP30A
2SA70	Ge-PNP	AM/FM,20V,10mA,70MHz	1g	Mat	AF124,AF200,AF106,AF306
2SA700	Si-PNP	AF,Sw-Pow,35V,1,5A,8W,11MHz	17j$	Hit	BD240,BD242,BD536,BD936,TIP30A...
2SA701(NP)	*Si-PNP*	*GenP,30V,0,05A,0,1W,80MHz*	7c	Sanyo	BC213,BC258,BC308,BC558..
2SA702(NP)	Si-PNP	=2SA701:50V	7c	Sanyo	BC212,BC257,BC307,BC557..

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2SA703	Si-PNP	AF,Sw-Pow,25V,1,5A,7W,70MHz	13I$	Mitsubishi	BD238
2SA704	Si-PNP	GenP,25V,0,2A,0,32W,140MHz	10b	Son	BC213,BC258,BC308,BC558..
2SA705	Si-PNP	=2SA704:50V	10b	Son	BC212,BC257,BC307,BC557..
2SA706	Si-PNP	GenP,Pow,40V,1A,7,9W,120MHz	13a$	Sony	BD416,BD508,BD516,BD526..
2SA706-2	Si-PNP	GenP,Pow,60V,1A,7,9W,120MHz	13a$	-	BD416,BD518,BD526,BD530..
2SA706-3	Si-PNP	GenP,Pow,80V,1A,7,9W,120MHz	13a$	-	BD418,BD520,BD528,BD530..
2SA706-4	Si-PNP	GenP,Pow,100V,1A,7,9W,120MHz	13a$	-	BD420,BD530
2SA707	Si-PNP	GenP-Dr/Out,40V,0,5A,0,75W,180MHz	7co	Nec	BC327,BC636,2SA1515,2SB910,..
2SA708	Si-PNP	GenP,80V,0,7A,0,8W,100MHz	2a$	Nec,Mic	BC303,BCX60,2N3634..37,2SA606..
2SA708A	Si-PNP	=2SA708:100V,95MHz	2a$	-	BCX60,BSS17,2N3634..37,2SA606..
2SA709	Si-PNP	HF/Sw,60V,0,2A,0,3W,280MHz	7a	Nec	BC212,BC256,BC266,BC556..
2SA71	Ge-PNP	FM,20V,10mA,100MHz	1g	Mat	AF124,AF200,AF106,AF306
2SA710	Si-PNP	HF/Sw,50V,0,1A,600MHz,<80/180nS	2a	Nec	BFS16,BF606,BSW24,2N3250A..51A..
2SA711	Si-PNP	=2SA710:1000MHz,<70/170nS	2a$	Nec	BFS16,BF606,BSW24,2N3250A..51A..
2SA712	Si-PNP	Sw,150V,0,5A,0,75W,110/350nS	2a$	Nec	BFT19,BFT28,2N3636..3637,2N5415
2SA713(S)	Si-PNP-Darl	15V,0,3A,0,25W,180MHz,B=20000	7c	Nec	BCS16,BC876,2SA790,2SA830..
2SA713A(AS)	Si-PNP-Darl	=2SA713:40V,B=30000	7c	-	BCS16,BC876,2SA790,2SA830..
2SA714	Si-PNP	AF,Sw-Pow,150V,7A,60W,8MHz	23a$	Sanyo	BD246D,MJ2955,2SB681,2SB695,2SB696,2SB816..
2SA714L	Si-PNP	=2SA714:100V	23a$	-	BD246C,2SB681,2SB695,2SB696,2SB816..
2SA715	Si-PNP	AF,Sw-Pow,35V,2,5A,10W,160MHz	14h$	Hit	BD376,MJE172,2SA1217,2SB1009,2SB1217..
2SA717	Si-PNP	GenP,60V,1A,0,8W,<60/160nS	2a$	Nec	2N4030..4033,2N4036..4037
2SA718	Si-PNP	GenP,60V,0,2A,0,3W,250MHz	2a$	Nec	BC212,BC556,BSW24,2N2906..2907..
2SA719(NC)	Si-PNP	GenP,30V,0,5A,0,625W,200MHz	7c	Mat,Mic	BC327..328,BC636,2SA1515,2SB910,..
2SA72	Ge-PNP	AM,18V,5mA,40MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA720	Si-PNP	60V,0.5A,0.6W,200MHz	-		-
2SA720(NC)	Si-PNP	=2SA719:60V	7c	Mat,Mic	BC327(A),BC638,2SB647,2SB910,..
2SA720A	Si-PNP	=2SA719:80V,120MHz	7c	-	BC640,2N5400,2SA695,2SB647,..
2SA721	Si-PNP	GenP,LN,35V,0,05A,0,15W,250MHz	7c	Mat,Mic	BC214,BC259,BC309,BC559..
2SA722	Si-PNP	=2SA721:55V	7c	Mat,Mic	BC214,BC416,BC560,2SA1136..37..
2SA723	Si-PNP	GenP,40V,0,5A,0,25W,180MHz	7c	Nec,Mic	BC327,BC636,2SA1515,2SB910,..
2SA724	Si-PNP	GenP,35V,0,05A,0,25W,300MHz	7c	Nec	BC213,BC258,BC308,BC558..
2SA725	Si-PNP	GenP,LN,35V,0,1A,0,2W,100MHz	7b	Mit	BC214,BC259,BC309,BC559..
2SA726	Si-PNP	=2SA725:50V	7b	Mit	BC214,BC416,BC560,2SA1136..37..
2SA728	SI-PNP	GenP,30V,0,1A,0,1W,100MHz	41c	Mit	BC213,BC258,BC308,BC558..
2SA728A	Si-PNP	=2SA728:60V,130/700nS	41c	-	BC212,BC556,BSW24,2N2906..2907..
2SA73	Ge-PNP	AM,18V,5mA,35MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA730	Si-PNP	=2SA719:0,6W	7co	Mat,Mic	→2SA719
2SA731	Si-PNP	=2SA720:0,6W	7co	Mat,Mic	→2SA720
2SA732	SI-PNP	GenP,40V,0,3A,0,65W,200MHz	2a$	Fui	BC160..161,BC303..304,2N2303..
2SA733	Si-PNP	GenP,60V,0,1A,0,25W,180MHz	7c	Nec,Mic	BC212,BC257,BC307,BC557..
2SA738	Si-PNP	AF,Sw-Pow,25V,1,5A,8W,160MHz	14h$	Hit	BD136,BD227,BD376,MJE172,2SB1009..
2SA739	Si-PNP	Sw,Pow,400/400V,3A,50W	23a$	Toshiba	BUW22..23,BUW32
2SA74	Ge-PNP	HF,50V,50mA,70MHz	4g	Tos	AF121(S),AF202(S),AFY18
2SA740(A)	Si-PNP	AF,Sw-Pow,150V,1,5A,25W,8MHz	17j$	Tos	BD240D,2SA940,2SB628(A),2SB861..
2SA741(N)	Si-PNP	Sw,20V,0,1A,0,36W,<70/120nS	2a$	Hit	BSW24,2N3209,2N4034..35,2N4125..26..
2SA742(N)	Si-PNP	Sw,60V,0,5A,0,7W,<40/100nS	2a$	Hit	2SA717
2SA743	Si-PNP	AF,Sw-Pow,50V,1A,8W,120MHz	14h$	Hit	BD138,BD229,BD238,BD376,2SB1007..
2SA743A	Si-PNP	=2SA743:80V	14h$	-	BD140,BD231,BD380,2SB1007..
2SA744	Si-PNP	AF,Sw-Pow,80V,8A,70W,15MHz	23a$	Sak	BD246B,BD314,2N5872,2SB681..
2SA745	Si-PNP	=2SA744:100V	23a$	Sak	BD246C,BD318,2N6229,2SB681..
2SA745A	Si-PNP	=2SA745:120V	23a$	-	BD246C,2N6230..31,2SB681,2SB696..
2SA746	Si-PNP	AF,Sw-Pow,80V,10A,100W,15MHz	23a$	Sak	BD246B,BD314,2N5876,2SB681..
2SA747	Si-PNP	=2SA746:120V	23a$	Sak	BD246C,2N6230..31,2SB681,2SB696..
2SA747A	Si-PNP	=2SA747:140V	23a$	-	BD246D,2N6231,2SA908,2SB681,2SB696..
2SA748	Si-PNP	AF,Sw-Pow,70V,2A,15W,120MHz	17j$	Mat	2SA1078,2SA1288,BD242B
2SA749	Si-PNP	Nix,Sw,100V,0,05A,0,25A,>40MHz	7c	Mat,Mic	BF398,BF423,2SA1017,2SB715..716..
2SA749A	Si-PNP	=2SA749:130V	7c	-	BF398,BF423,2SA1019,2SB716A..
2SA75	Ge-PNP	HF,20V,50mA,30MHz	4g	Tos	AF121(S),AF202(S),AFY18
2SA750	Si-PNP	GenP,LN,50V,0,05A,0,25W,100MHz	7c	Nec	BC214,BC416,BC560,2SA1136..37..
2SA751	Si-PNP	GenP,30V,1A,1W,200MHz	7co	Mat	BC327..328,BC636,2SB809,2SB1116,..
2SA752	Si-PNP	=2SA751:60V	7co	Mat	BC327A,BC638,2SB647,2SB734..
2SA753	Si-PNP	AF,Sw-Pow,140V,10A,100W,20MHz	23a$	Hit	BDX20,2SB681,2SB697,2SB817..
2SA754	Si-PNP	AF,Sw-Pow,50V,2A,20W,50MHz	17j$	Hit	BD240,2SA748,2SA1078,2SA1288..
2SA755	Si-PNP	=2SA754	17j$	Hit	BD240,BD242B,2SA748,2SA1078,2SA1288..

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2SA756	Si-PNP	AF,Sw-Pow,100V,6A,50W,20MHz	23a$	Hit	BD246C,BDW52C,BDX96,2N6229..31,2SB681..
2SA757	Si-PNP	AF,Sw-Pow,120V,7A,60W,24MHz	23a$	Hit	BD246C,BDX20,MJ2955,2N6230..31,2SB681..
2SA758	Si-PNP	AF,Sw-Pow,130V,7A,80W,20MHz	23a$	Hit	BDX20,MJ2955,2N6231,2SA982,2SB681..
2SA759	Si-PNP	GenP,60V,0,2A,200MHz	35a	NEC	BC856,BCW68,BCW89,2SA1620..
2SA76	Ge-PNP	FM,18V,5mA,130MHz	4g	Tos	AF124..125,AF106,AF306,2SA340..342
2SA762	Si-PNP	110V,2A,23W,80MHz	-		-
2SA765	Si-PNP	80V,6A,40W,10MHz	-		-
2SA777	Si-PNP	80V,0.5A,0.75W,120MHz	-		-
2SA778A	Si-PNP	180V,0.05A,0.2W,60MHz	-		-
2SA781	Si-PNP	20V,0.2A,0.2W,<80/16µS	-		-
2SA784	Si-PNP	=2SA782:25V	9c	Rhm	BC213,BC258,BC308,BC558..
2SA785	Si-PNP	GenP,80V,0,05A,0,15W,180MHz	9c	Rhm	BC556,2SA893(A),2SB715..716(A)..
2SA786	Si-PNP	=2SA785:50V	9c	Rhm	BC212,BC257,BC307,BC557..
2SA787	Si-PNP	=2SA785:25V	9c	Rhm	BC213,BC258,BC308,BC558..
2SA788	Si-PNP	GenP,LN,50V,0,03A,0,15W,200MHz	9c	Rhm	BC214,BC416,BC560,2SA1136..37..
2SA789	Si-PNP	=2SA788:25V	9c	-	BC214,BC259,BC309,BC559..
2SA79	Ge-PNP	Sw,20V,Ueb=12V,0,2A,>4MHz	2a	Tos	ASY26..27,ASY48,ASY76..77
2SA790(M)	Si-PNP-Darl	GenP,40V,0,3A,0,3W,B>1000	9c	Rhm	BC516,MPSA75..77,2SA1555,2SB1076,..
2SA791	Si-PNP-Darl	=2SA790:25V	9c	Rhm	BC516,BC876,MPSA75..77,2SB1076..
2SA793	Si-PNP	GenP,80V,0,6A,0,8W,100MHz	2a$	Fui	BC303,BSV17,2N3634..37,2SA606..
2SA794	Si-PNP	AF,Sw-Pow,100V,0,5A,5W,120MHz	14h$	Mat	BD140,BD231,BD380,2SB874..875
2SA794A	Si-PNP	=2SA794:120V	14h$	-	2SA1178,2SA1184,2SA1220(A),2SA1358
2SA795	Si-PNP	AF,Sw-Pow,150V,0,25A,10W,120MHz	14h$	Mat	2SA1178,2SA1220A,MJE350
2SA795A	Si-PNP	=2SA795:180V,1A	14h$	-	2SA1249,2SB649
2SA796	Si-PNP-Darl	Sw,30V,0,3A,0,3W,B=40000	7c	Njr	BC516,BC876,MPSA75..77,2SB1076..
2SA797	Si-PNP	HF,90V,0,05A,0,15W,100MHz	2a	Mit	BF397..398,BF423,BS568,2SA893..
2SA798	Si-PNP	Dual,LN,50V,0,1A,0,4W,100MHz	S-SIP	Mit	-
2SA799(F)	Si-PNP	Sw,60V,1,5A,1W,<45/110nS	2a$	Fui	2N3720
2SA80	Ge-PNP	AM-Amp,20V,10mA,60MHz	4g	Hit	AF124..126,AF200,2SA218..227
2SA800	Si-PNP	UHF-A,20V,0,03A,2,5GHz	5g	Nec	BFQ78,BFR99,2SA967,2SA1058
2SA801	Si-PNP	UHF-A,20V,0,05A,4GHz	51s	Nec	BFQ32,2SA1057,2SA1223
2SA802	Si-PNP	Mix,Sw,130V,0,03A;0,15W,50MHz	9c	Rhm	BF398,BF423,BF435..437,2SA1370..
2SA803	Si-PNP	=2SA802:200MHz	9c	Rhm	BF398,BF423,BF435..437,2SA1370..
2SA804	Si-PNP	=2SA802:180MHz	9c	Rhm	BF398,BF423,BF435..437,2SA1370..
2SA805	Si-PNP	=2SA802:180V	9c	Rhm	BF423,BF436..437,2SA1370..1371..
2SA806	Si-PNP	=2SA802:210V	9c	Rhm	BF423,BF436..437,2SA1370..1371..
2SA807	Si-PNP	AF,Sw-Pow,60V,6A,50W,10MHz	23a$	Sak	BD246A,BD312,BDWS2C,BDX92,2N5871..72..
2SA808	Si-PNP	=2SA807:80V	23a$	Sak	BD246B,BD314,BDW52C,BDX94,2N5872..
2SA808A	Si-PNP	=2SA808:100V	23a$	-	BD246C,BD318,BDX96,2N6229..30..
2SA809	Si-PNP	Sw,Vid,150/120V,0,05A,0,7W,100MHz	2ao	Fui	(BF470,BF818,BF870,2SA1406..07,..)
2SA81	Ge-PNP	AM-Osc,20V,10mA,40MHz	4g	Hit	AF124..126,AF200,2SA218..227
2SA810	Si-PNP	=2SA809:150/150V	2ao	Fui	(BF470,BF818,BF870,2SA1406..07,..)
2SA811	Si-PNP	GenP,50V,0,03A,100MHz	35a	NEC	BC856..857,BCW69..70,BCW89..
2SA811A	Si-PNP	=2SA811:120V,90MHz	35a	-	2SA1312,2SA1566
2SA811A-C15	Si-PNP	-	35	Nec	→2SA811A
2SA811A-C16	Si-PNP	-	35	Nec	→2SA811A
2SA811A-C17	Si-PNP	-	35	Nec	→2SA811A
2SA811A-C18	Si-PNP	-	35	Nec	→2SA811A
2SA811-C5	Si-PNP	-	35	Nec	→2SA811
2SA811-C6	Si-PNP	-	35	Nec	→2SA811
2SA811-C7	Si-PNP	-	35	Nec	→2SA811
2SA811-C8	Si-PNP	-	35	Nec	→2SA811
2SA812	Si-PNP	GenP,60V,0,1A,180MHz	35a	Nec	BC856,BCW89,2SA1311
2SA812-M3	Si-PNP	-	35	Nec	→2SA812
2SA812-M4	Si-PNP	-	35	Nec	→2SA812
2SA812-M5	Si-PNP	-	35	Nec	→2SA812
2SA812-M6	Si-PNP	-	35	Nec	→2SA812
2SA812-M7	Si-PNP	-	35	Nec	→2SA812
2SA813	Si-PNP	GenP,60V,0,2A,200MHz	35a	NEC	BCW68,2SA1620
2SA813-S2	Si-PNP	-	35	Nec	→2SA813
2SA813-S3	Si-PNP	-	35	Nec	→2SA813
2SA813-S4	Si-PNP	-	35	Nec	→2SA813
2SA814	Si-PNP	AF,Sw-Pow,120V,1A,15W,30MHz	17j$	Tos	BD942,TIP32C,2SA839,2SA940,2SB536..537..
2SA815	Si-PNP	=2SA814:100V	17f$	Tos	BD240C,BD242C,BD940,TIP30C,2SB536..537,..

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2SA816	Si-PNP	AF,Sw-Pow,80V,0,75A,10W,100MHz	17f$	Tos,Mic	BD240B,BD242B,BD938,TIP30C,2SB536..537,..
2SA817	Si-PNP	GenP,80V,0,3A,0,6W,100MHz	7c	Tos,Mic	BC640,2N5400..01,2SA1683,2SB910..
2SA817A	Si-PNP	=2SA817:0,4A,0,8W	7c(9mm)	-	BC640,2N5400..01,2SA965,2SA1533..
2SA818	Si-PNP	Vid,180V,0,05A,120MHz	13g$	Toshiba	BF463..465,MJE350,MPSU60,2SA964(A)..
2SA819	Si-PNP	GenP,40V,0,3A,0,3W,240MHz	7c	Rhm	BC327,BC636,2SA1515,2SA1683,..
2SA82	Ge-PNP	AM-Mix,20V,10mA,40MHz	4g	Hit	AF124..126,AF200,2SA218..227
2SA820	Si-PNP	=2SA805:	7c	Rhm	→2SA805
2SA822	Si-PNP	GenP,80V,0,03A,0,25W,200MHz	7c	Rhm	BC556,2SA893(A),2SB715..716(A)..
2SA823	Si-PNP	=2SA822:50V	7c	Rhm	BC212,BC257,BC307,BC557..
2SA824	Si-PNP	=2SA822:30V	7c	Rhm	BC213,BC258,BC308,BC558..
2SA825(S)	Si-PNP	=2SA785:S:Fig.41c	7c,41c	Rhm	→2SA785
2SA826	Si-PNP	=2SA786:	7c	Rhm	→2SA786
2SA827	Si-PNP	GenP,25V,0,05A,0,25W,180MHz	7c	Rhm	BC213,BC258,BC308,BC558..
2SA828	Si-PNP	GenP,LN,50V,0,03A,0,25W,180MHz	7c	Rhm	BC214,BC416,BC560,2SA1136..37..
2SA829	Si-PNP	=2SA828:25V	7c	Rhm	BC214,BC259,BC309,BC559,2SA1137+
2SA83	Ge-PNP	AM-IF,25V,10mA,30MHz	4g	Hit	AF124..127,AF200,2SA218..227
2SA830(S)	Si-PNP-Darl	=2SA790:S:Fig.41c	7c,41c	Rhm	→2SA790
2SA831	Si-PNP-Darl	=2SA791:	7c	Rhm	→2SA791
2SA832	Si-PNP	=2SA802:	7c	Rhm	→2SA802
2SA833	Si-PNP	GenP,130V,0,03A,0,25W,200MHz	7c	Rhm	BF398,BF423,2SA1019,2SB716A..
2SA834	Si-PNP	=2SA833:0,05A	7c	Rhm	BF398,BF423,2SA1019,2SB716A..
2SA835	Si-PNP	Sw,Vid-Pow,140V,0,5A,7,9W	13g$	Sony	BF463..465,MJE350,MPSU60,2SA964(A)..
2SA836	Si-PNP	GenP,LN,55V,0,1A,0,2W,200MHz	9b,7c	Hit	BC214,BC416,BC560,2SA1136..37..
2SA837	Si-PNP	AF,Sw-Pow,90V,4A,50W(Tc=75°),10MHz	23a$	Mat	BD246C,BD314,BDW52C,BDX96,2N6226..27..
2SA838	Si-PNP	GenP,30V,0,03A,0,25W,300MHz	7c	Mat	BC308,BC558,BF324,BF450..451..
2SA839	Si-PNP	AF,Sw-Pow,150V,1,5A,25W,6MHz	17j$	Tos	BD240D,TIP32C,2SA940,2SB608,2SB628(A),2SB861
2SA84	Ge-PNP	AM-Amp,25V,10mA,35MHz	4g	Hit	AF124..126,AF200,2SA218..227
2SA840	Si-PNP	Vid,140V,0,5A,0,75W,45MHz	7c(9mm)	Son	BF491..493,BF423A,MPSA92..93..
2SA841	Si-PNP	AF,LN,60V,0,05A,0,2W,140MHz	7c	Tos	BC214,BC416,BC560,2SA1136..37..
2SA842	Si-PNP	=2SA841:40V	7c	Tos	BC214,BC416,BC560,2SA1136..37..
2SA843	Si-PNP	TV-VD-Out,200V,0,5A,20W,35MHz	17j$	Mat	BD240F,2SA968B,2SA1133,2SB861
2SA844	Si-PNP	GenP,55V,0,1A,0,3W,200MHz	9b,7c	Hit	BC212,BC257,BC307,BC556..
2SA845	Si-PNP	Vid,150V,0,05A,0,2W,>40MHz	2a	Hit	BF398,BF423,BF435..437,2SA1370..
2SA845A	Si-PNP	=2SA845:180V	2a	-	BF423,BF436..437,2SA1370..71..
2SA847	Si-PNP	GenP,LN,90V,0,05A,0,2W,150MHz	7b	Mit	2SA872(A),2SA941..942,2SA970..
2SA847A	Si-PNP	=2SA847:120V	7b	-	2SA872A,2SA941,2SA970,2SA1016..
2SA848	Si-PNP	Vid,150/120V,0,05A,1W,100MHz	2ao	Fui	2SA1123..24,2SA1281,2SA1285A,2SA1370+
2SA849	Si-PNP	=2SA848:150/150V	2ao	Fui	2SA1123..24,2SA1281,2SA1285A,2SA1370+
2SA85	Ge-PNP	AM,25V,10mA,55MHz	4g	Hit	AF124..126,AF200,2SA218..227
2SA850	Si-PNP	GenP,100V,0,5A,0,8W,130MHz	7b	Mit	BC640,2SA1708,2SB647,2SB984..
2SA851	Si-PNP	GenP,50V,0,1A,0,3W,150MHz	7a	Mit	BC212,BC257,BC307,BC557..
2SA852	Si-PNP	=2SA852:35V	7a	Mot	BC213,BC258,BC308,BC558..
2SA853	Si-PNP	=2SA852:35V,ra	7a	Mit	BC214,BC259,BC309,BC559,2SA970..
2SA855	Si-PNP	GenP,60V,0,05A,0,15W,140MHz	2a	Tos	BC212,BC256,BC266,BC556..
2SA856(A)	Si-PNP	=2SA855:50V,ra	2a	Tos	BC214,BC416,BC560,2SA1136..37..
2SA857	Si-PNP	Vid,150/120V,0,05A,0,5W,100MHz	7c	Fui	BF398,BF423,BF435..437,2SA1370..
2SA858	Si-PNP	=2SA857:150/150V	7c	Fui	BF398,BF423,BF435..437,2SA1370..
2SA859	Si-PNP	=MPSA92	7e	Mot	→MPSA92
2SA86	Ge-PNP	HF,45V,50mA,35MHz	4go	Hit	AF121(S),AF202(S),AFY18
2SA860	Si-PNP	=MPSA93	7e	Mot	→MPSA93
2SA861	Si-PNP	AF,Sw-Pow,20V,2A,80MHz	13j$	Sony	2SA473,2SA699,2SA748,2SA887..
2SA866	Si-PNP	GenP,30V,0,1A,0,3W,150MHz	7e	Njr	BC213,BC258,BC308,BC558..
2SA867	Si-PNP	=2SA866:60V	7e	Njr	BC212,BC256,BC266,BC556..
2SA868	Si-PNP	=2SA866:90V	7e	Njr	2SA970,2SA1136..1137,2SA1285(A)..
2SA869	Si-PNP	GenP,30V,0,4A,0,5W,150MHz	7e	Njr	BC327..328,BC636,2SA1515,2SB910,..
2SA87	Ge-PNP	FM-Preamp,30V,10mA,100MHz	4g	Hit	AF124,AF106,AF306,2SA340..342
2SA870	Si-PNP	=2SA869:60V	7e	Njr	BC327,BC638,2SA1683,2SB910..
2SA871	Si-PNP	GenP,LN,30V,0,05A,0,2W,120MHz	7e	Njr	BC214,BC259,BC309,BC559,2SA970..
2SA872	Si-PNP	GenP,LN,90V,0,05A,0,3W,120MHz	7c	Hit	2SA941..942,2SA970,2SA1016,2SA1038,..
2SA872A	Si-PNP	=2SA872:120V	7c	-	2SA941,2SA970,2SA1016,2SA1038..
2SA873	Si-PNP	GenP,60V,0,2A,0,3W,220MHz	7a	Fui	BC212,BC256,BC266,BC556..
2SA874(M)	Si-PNP	=2SA854:0,3W	9c	Rhm	→2SA854
2SA876(H)	Si-PNP	GenP,70V,0,5A,0,35W,200MHz	2a$	Hit	BC640,BCX39,2N5400..01,2SB649..
2SA877	Si-PNP	AF,Sw-Pow,80V,10A,100W,15MHz	23a$	Sak	BD246B,BD314,BDW52C,2N5876,2SB555..556..

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2SA878	Si-PNP	=2SA877:120V	23a$	Sak	BD246C,2N6230..31,2SB555..56,2SB681..
2SA879	Si-PNP	Vid,250/200V,0,07A,1W,80MHz	7c(9mm)	Mat	BF436..437,BF423A,2SA1371..
2SA88	Ge-PNP	FM-Osc,30V,10mA,100MHz	4g	Hit	AF124..125,AF106,AF306,2SA340..342
2SA880	Si-PNP	GenP,LN,35V,0,05A,0,15W,120MHz	9c	Mat	BC214,BC259,BC309,BC559,2SA970..
2SA881	Si-PNP	GenP,40V,1A,0,6W,150MHz	9c	Rhm	BC636,BC638,2SA647,2SB1116..
2SA882	Si-PNP	AF,Sw-Pow,130V,7A,100W,7MHz	23a$	Mat	BD246D,2SA982,2SB681,2SB695,2SB696..
2SA883	Si-PNP	GenP,60V,0,2A,0,3W,280MHz	7c	Nec	BC212,BC256,BC266,BC556..
2SA884	Si-PNP	Dual,65V,0,2A,0,27W,140MHz	6-DIP	Son	-
2SA885	Si-PNP	AF,Sw-Pow,45V,1A,5W,200MHz	14h$	Mat	BD136,BD227,BD376,BD438,2SB1007..
2SA886	Si-PNP	AF,Sw-Pow,50V,1,5A,5W,150MHz	14h$	Mat	BD138,BD229,BD376,BD438,2SB744(A)..
2SA887	Si-PNP	AF,Sw-Pow,70V,2A,10W,150MHz	13j$	Matsushita	BD242B
2SA888	Si-PNP	GenP,25V,0,05A,0,35W,100MHz	7e	Mat,Mic	BC213,BC258,BC308,BC558..
2SA889	Si-PNP	=2SA888:45V	7e	Mat,Mic	BC212,BC257,BC307,BC557..
2SA89	Ge-PNP	FM-Mix,30V,10mA,80MHz	4g	Hit	AF124..125,AF106,AF306,2SA340..342
2SA890	Si-PNP	GenP,30V,0,5A,0,625W,200MHz	7e	Mat,Mic	BC327..328,BC636,2SA1515,2SB910,..
2SA891	Si-PNP	=2SA890:60V	7e	Mat,Mic	BC327A,BC638,BC640,2SB647..
2SA892	Si-PNP-Darl	Sw,Pow,40V,6A,40W,B>300	17j$	Sak	BD644,BD896,BDW24,BDW64,2SB1339+
2SA893	Si-NPN	GenP,LN,90V,0,05A,0,3W,120MHz	7c	Hit	2SA941..942,2SA970,2SA1016,2SA1038,..
2SA893A	Si-PNP	=2SA893:120V	7c	-	2SA941,2SA970,2SA1016,2SA1038..
2SA894	SI-PNP	GenP,30V,1A,0,6W,150MHz	7c	Njr	BC636,BC638,2SB647,2SB909..
2SA895	Si-PNP	VHF,30V,30mA,500MHz	7c	Njr	BF324,BF414,BF506,BF914,BF936..
2SA896(-1,-2)	Si-PNP	Vid,200V,0,1A,0,75W,70MHz	7c(9mm)	Son	BF436..437,BF423A,2SA1370..71..
2SA897	Si-PNP	AF,Sw-Pow,60V,2A,0,95W,55MHz	13j$	Sony	2SA748,2SA887,2SA1078,2SA1288..
2SA898	Si-PNP	Vid-Pow,150/120V,0,05A,100MHz	14h$	Fui	BF470,BF472,BF416,BF418,MJE350...
2SA899	Si-PNP	=2SA898:150/150V	14h$	Fui	BF470,BF472,BF416,BF418,MJE350
2SA90	Ge-PNP	HF,30V,20mA,>60MHz	4go	Hit	AF124..126,AF106,AF306,2SA340..342
2SA900	Si-PNP	AF,Sw-Pow,20V,1A,4W,200MHz	14h$	Mat	BD136,BD227,BD376,MJE210,2SB1009..
2SA901	Si-PNP	GenP,40V,0,1A,0,2W,100MHz	7b	Mit	BC213,BC257,BC307,BC557..
2SA902	SI-PNP	=2SA903:ra	7c	Mit	BC214,BC416,BC560,2SA1136..37..
2SA903	Si-PNP	GenP,50V,0,1A,0,2W,150MHz	7c	Mit	BC212,BC257,BC307,BC557..
2SA904	Si-PNP	GenP,90V,0,05A,0,2W,150MHz	7b	Mit	2SA893(A),2SA970,2SB715..716(A)..
2SA904A	Si-PNP	=2SA904:120V	7b	-	2SA893A,2SA970,2SA1017,2SB716(A)..
2SA905	Si-PNP	Vid,120V,0,05A,0,8W,200MHz	7b	Mit	BF398,2SA893A,2SA970,2SA1017..
2SA906	Si-PNP	GenP,LN,40V,0,1A,0,2W,100MHz	7b	Mit	BC214,BC416,BC560,2SA1136..37..
2SA907	Si-PNP	AF,Sw-Pow,100V,15A,150W,10MHz	23a$	Sak	BD318,MJ2955,2N6029..6031..
2SA908	Si-PNP	=2SA907:150V	23a$	Sak	MJ15016,2N6609,2SA1147,2SB645..
2SA909	Si-PNP	=2SA907:200V	23a$	Sak	MJ15016,2SA1116..1117,2SB552,2SB645+
2SA911	Si-PNP	Sw,850/550V,0,1A,0,47W,9MHz	2a$	Son	-
2SA912(NC)	Si-PNP	AF,LN,150V,0,05A,0,75W,200MHz	7c(9mm)	Mat	2SA1016K,2SA1123..1124,2SA1482
2SA913	Si-PNP	AF,Sw-Pow,150V,1A,15W,120MHz	17j$	Mat	2SA968(A,B),2SA1111..1112,2SB628(A),..
2SA913A	Si-PNP	=2SA913:180V	17j$	-	2SA968A,B,2SA1011,2SA1112,2SB628A
2SA914	SI-PNP	AF,150V,0,05A,200MHz	14h$	Mat	BF470,BF472,BF416,BF418..
2SA915	Si-PNP	AF,120V,0,05A,1W,80MHz	9b	NEC	2SA1016..17,2SA1123..24,2SB1348..
2SA916	Si-PNP	AF,160V,0,05A,1W,80MHz	9b	NEC	2SA1123..24,2SA1281,2SB1348
2SA917	Si-PNP	Vid,120V,0,1A,0,75W70MHz	7c(9mm)	Son	BF398,2SA970,2SA1136,2SA1285(A)..
2SA918	Si-PNP	GenP,40V,0,3A,0,3W,200MHz	7a	Fui	BC327,BC636,2SA1515,2SA1683,..
2SA919	Si-PNP	Sw,Pow,850V,0,1A,0,95W,9MHz	13g$	Sony	-
2SA92	Ge-PNP	AM-Osc,18V,5mA,50MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA920	Si-PNP	AF,Sw-Pow,200V,0,5A,7,9W,40MHz	13g$	Sony	BF463..464,MPSU60
2SA921	Si-PNP	GenP,LN,120V,0,02A,0,25W,200MHz	7c	Mat	2SA941,2SA970,2SA1016,2SA1038..
2SA922(-1,-2)	Si-PNP	AF-Dr/Out,80..100V,1A,0,625W,120MHz	2a$	Son	BCX60,BSS17,BSW40,2N3634..37..
2SA923(-1,-2)	Si-PNP	Sw,Vid,200V,0,2A,0,625W,70MHz	2a$	Son	BFQ36..37,(BF616,BF618,MPSU60,..)
2SA924	Si-PNP	GenP,30V,0,1A,0,5W,120MHz	7a	Hit	BC213,BC258,BC308,BC558..
2SA925(-1,-2)	Si-PNP	VHF/Sw,30..45V,30mA,0,25W,500MHz	7c	Son	BF324,BF414,BF506,BF914,BF936..
2SA927	Si-PNP	GenP,60V,0,25A,0,5W,290MHz	7c	Fui	BC212,BC256,BC266,BC556..
2SA928	Si-PNP	HF,20V,1A,0,25W	7c	Son	-
2SA929	SI-PNP	GenP,LN,55V,0,05A,0,2W,80MHz	7c	Sanyo	BC416,BC560,2SA970,2SA1136..37..
2SA93	Ge-PNP	AM-Mix,18V,5mA,45MHz	4g	Tos	AF124..126,AF200,2SA218..227
2SA930	Si-PNP	=2SA929:40V	7c	Sanyo	BC214,BC416,BC560,2SA1136..37..
2SA931	Si-PNP	Vid,150/120V,0,05A,0,45W,>70MHz	2a	Fui	BF398,BF423,BF435..437,2SA1370..
2SA932	Si-PNP	=2SA931:150/150V	2a$	Ful	BF398,BF423,BF435..437,2SA1370..
2SA933	Si-PNP	50V,0.1A,0.3W	-		-
2SA933(A,S,AS)	Si-PNP	GenP,50(A=60)V,0,1A,0,3W,140MHz	7c,41c	Rhm	BC212,BC256,BC307,BC557..
2SA933(S)LN	Si-PNP	=2SA933:ra	7c,41c	-	BC416,BC560,2SA1039,2SA1137..

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2SA934	Si-PNP	GenP, 40V, 1A, 0,75W, 150MHz	7c(9mm)	Rhm	BC327, 2SA1287, 2SB978, 2SB1041..
2SA935	Si-PNP	=2SA934: 80V, 0,7A	7c(9mm)	Rhm	BC640, 2SA965, 2SB647, 2SB1041..
2SA936	Si-PNP-Darl	GenP, 40V, 0,3A, 0,3W, B>10000	7c	Rhm	BC516, BC876, MPSA75..77, 2SB1076,..
2SA937	Si-PNP	50V, 0.1A, 0.3W, 140MHz	-		-
2SA937(M)	Si-PNP	=2SA933:	9c	Rhm	→2SA933
2SA937LN,MLN	Si-PNP	=2SA933: ra	9c	Rhm	→2SA933LN
2SA938	SI-PNP	GenP, 50V, 0,5A, 0,5W	7c	Son	BC327, BC638, 2SA1683, 2SB647..
2SA939	Si-PNP	Vid, 250V, 0,05A, 130MHz	14h$	Fui	BF470, BF472, BF416, BF418, MJE350…
2SA94	Ge-PNP	HF, 9V, 10mA, 45MHz	4g	Hit	AF124..127, AF200, 2SA218..227
2SA940	Si-PNP	TV-VD, AF, Sw, Pow, 150V, 1,5A, 25W, 4MHz	17j$	Tos	2SA839, 2SB608, 2SB628(A), 2SB861
2SA940A	Si-PNP	=2SA940: lso	17c	-	2SA1306, 2SA1332, 2SA1606, 2SB1338..
2SA941	Si-PNP	GenP, LN, 120V, 0,05A, 0,3W, 150MHz	7c	Tos	2SA872A, 2SA992, 2SA1016, 2SA1038,..
2SA942	Si-PNP	=2SA941: 90V	7c	Tos	2SA872(A), 2SA992, 2SA1016, 2SA1038,..
2SA949	Si-PNP	AF-Dr/Vid, 150V, 0,05A, 0,8W, 120MHz	7c(9mm)	Tos	2SA1019, 2SA1124, 2SA1285A, 2SA1482..
2SA95	Ge-PNP	HF, 20V, 10mA, 50MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA950	Si-PNP	GenP, 35V, 0,8A, 0,6W, 120MHz	7c	Tos,Mic	BC327..328, BC636, BC638, 2SB647..
2SA951	Si-PNP	AF, Sw-Pow, 140V, 0,5A, 45MHz	13j$	Sony	2SA913(A), 2SA1111..1112, 2SA1195..
2SA952	Si-PNP	GenP, 30V, 0,7A, 0,6W, 160MHz	7c	Nec	BC327..328, BC636, 2SB909..910..
2SA953	Si-PNP	GenP, 60V, 0,3A, 0,6W, 100MHz	7c	Nec	BC327A, BC638, 2SA1683, 2SB647..
2SA954	Si-PNP	=2SA953: 80V	7c	Nec	BC640, BCX39, 2N5400..01, 2SB647..
2SA956	Si-PNP	GenP, 60V, 0,1A, 280MHz	35a	Nec	BC856, BCW89, 2SA1311..12
2SA956-H3	Si-PNP	-	35	Nec	→2SA956
2SA956-H4	Si-PNP	-	35	Nec	→2SA956
2SA956-H5	Si-PNP	-	35	Nec	→2SA956
2SA956-H6	Si-PNP	-	35	Nec	→2SA956
2SA957	Si-PNP	AF, Sw-Pow, 150V, 2A, 30W, 20MHz	17j$	Sak	2SA1079, 2SA1133, 2SB628, 2SB861..
2SA958	Si-PNP	=2SA957: 200V	17j$	Sak	2SA1133, 2SB861
2SA959	SI-PNP	Sw, Pow, 100V, 10A, 100W	23a$	NEC	BUW96, MJ15016, 2SA1116..17, 2SA1147..
2SA96	Ge-PNP	HF, 20V, 10mA, 45MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA962	Si-PNP	GenP, Pow, 60V, 1,5A, 100MHz	13g$	Toshiba	BD518, BD520, BD526, BD528, BD530
2SA962A	SI-PNP	=2SA962	13g$	-	(BD816, BD818, BD842, BD844, 2SA887)
2SA963	Si-PNP	AF, Sw-Pow, 50V, 1,5A, 10W, 150MHz	14h$	Mat	BD138, BD229, BD376, MJE172, 2SB874..875..
2SA964	Si-PNP	Vid-Pow, 200V, 0,2A, 10W, 100MHz	13g$	NEC	BF463..465, MPSU60
2SA964A	Si-PNP	=2SA964: 250V	13g$	-	BF463..465, MPSU60
2SA965	Si-PNP	GenP, 120V, 0,8A, 0,9W, 120MHz	7c(9mm)	Tos	2SA1013, 2SA1275, 2SB647, 2SB1212
2SA966	Si-PNP	AF-Dr/Out, 30V, 1,5A, 0,9W, 120MHz	7c(9mm)	Tos	2SA1382, 2SB978, 2SB892, 2SB1312, TIP32A
2SA967	Si-PNP	UHF-A, 15V, 0,03A, 4GHz	24b	Tos	BFQ23, BFQ56, BFQ75..76
2SA968	Si-PNP	AF, Sw-Pow, 160/160V, 1,5A, 25W, 100MHz	17j$	Tos	2SA1011, 2SA1133, 2SA1112, 2SA1332
2SA968A	Si-PNP	=2SA968: 180/180V	17j$	-	2SA1011, 2SA1133, 2SA1112, 2SB628A
2SA968B	Si-PNP	=2SA968: 200/200V	17j$	-	2SA1133, 2SB861
2SA969	Si-PNP	=2SA968:	22a$	Tos	2SA1011, 2SA1133, 2SA1112, 2SA1332
2SA97	Ge-PNP	HF, 20V, 10mA, 40MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA970	Si-PNP	GenP, LN, 120V, 0,1A, 0,3W, 100MHz	7c	Tos	2SA1038, 2SA1049, 2SA1123, 2SA1136..
2SA971	Si-PNP	AF, Sw-Pow, 150V, 15A, 150W, 10MHz	23a$	Sak	MJ15016, 2SA908..909, 2SA1116..17..
2SA972	Si-PNP	GenP, 30V, 0,1A, 0,25W, 150MHz	7c	Mat	BC213, BC257, BC308, BC558..
2SA973	Si-PNP	GenP, LN, 60V, 0,05A, 0,25W	7c	Mat	BC214, BC416, BC560, 2SA1136..1137,..
2SA977	Si-PNP	AF-Pow, 180V, 0,05A, 80MHz	14h$	Mat	BF470, BF472, 2SA1352..53, 2SA1361..
2SA977A	Si-PNP	=2SA977: 220V	14h$	-	BF470, BF472, 2SA1353, 2SA1361..
2SA978	Si-PNP	GenP,LN, 40V, 0,1A, 0,2W, 125MHz	7b	Mit	BC214, BC416, BC560, 2SA1136..1137,..
2SA979	Si-PNP	Dual, LN, 100V, 0,05A, 0,4W, 150MHz	5-SIP	Mit	-
2SA98	Ge-PNP	HF, 20V, 10mA, 30MHz	1g	Fui	AF124..127, AF200, 2SA218..227
2SA980	Si-PNP	AF, Sw-Pow, 100V, 8A, 80W, 20MHz	23a$	Sak	BD246C, BDW52C, 2SB555..556, 2SB681,..
2SA981	Si-PNP	=2SA980: 120V	23a$	Sak	BD246D, 2N6230..31, 2SB555..56, 2SB681..
2SA982	Si-PNP	=2SA980: 140V	23a$	Sak	BD246D, 2N6231, 2SB555, 2SB681, 2SB697..
2SA983	Si-PNP	UHF, AGC, 30V, 20mA, 1GHz	25u	Nec	BF479..480, BF679..680, BF967..970,..
2SA984	Si-PNP	GenP, 60V, 0,5A, 0,6W, 120MHz	7c	Sanyo	BC638, 2N5400..01, 2SB647, 2SB1116,..
2SA984K	Si-PNP	=2SA984: 100V	7c	-	BC640, 2N5400..01, 2SA840, 2SB647..
2SA985	Si-PNP	AF/HF-Pow, 120V, 1,5A, 25W, 180MHz	17j$	Nec	2SA968, 2SA1078..1079, 2SB628(A)..
2SA985A	Si-PNP	=2SA985: 150V	17j$	-	2SA968, 2SA1079, 2SA1133, 2SB628(A),..
2SA986	Si-PNP	AF, Sw-Pow, 130V, 7A, 80W, 60MHz	19j$	Nec	2SB618, 2SB758A
2SA987	Si-PNP	GenP, 40V, 0,1A, 0,5W, 90MHz	7c	Nec	BC213, BC257, BC307, BC557..
2SA988	Si-PNP	GenP, 120V, 0,05A, 0,5W, 100MHz	7c	NEC	BF423, 2SA893A, 2SA970, 2SB717(A)..
2SA989	Si-PNP	GenP, 60V, 0,1A, 0,25W, 180MHz	7c	Nec	BC212, BC256, BC266, BC556..
2SA99	Ge-PNP	HF, 20V, 10mA, 20MHz	1g	Fui	AF124..127, AF200, 2SA218..227

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2SA990	Si-PNP	GenP,LN,60V,0,1A,0,25W,180MHz	7c	Nec	BC214,BC416,BC560,2SA1136..1137,..
2SA991	Si-PNP	GenP,LN,60V,0,1A,0,5W,90MHz	7c	Nec	BC214,BC416,BC560,2SA1136..1137,..
2SA992	Si-PNP	GenP,LN,120V,0,05A,0,5W,100MHz	7c	Nec	2SA872A,2SA941,2SA970,2SA1136..
2SA993	Si-PNP	GenP,50V,0,5A,0,625W,120MHz	7e	Hit	BC327,BC638,2SA1683,2SB1116,..
2SA994	Si-PNP	GenP,40V,0,3A,0,5W,120MHz	7b	Mit	BC327,BC638,2SA1683,2SB1116,..
2SA995	Si-PNP	Dual,100V,0,05A,0,4W,100MHz	5-SIP/bd	Mit	-
2SA997	Si-PNP	GenP,20V,1A,0,5W,150MHz	7c	Fui	BC636,BC638,2SB647,2SB909..910,..
2SA998	Si-PNP	=2SA997:50V	7c	Fui	BC636,BC638,2SB647,2SB910,..
2SA999	Si-PNP	GenP,50V,0,2A,0,3W,200MHz	7c	Mit	BC212,BC257,BC307,BC557..
2SA999L	Si-PNP	=2SA999:ra	7c	-	BC416,BC560,2SA970,2SA1136..1137,..
2SB100	Ge-PNP	AF,LN,30V,0,05A,0,1W	2a&	Nec	AC125..126,AC151r,ACY32,2SB173
2SB1000	Si-PNP	GenP,25V,1A,200MHz	39b	Hit	BC869,BCX51..53,BCX69,2SA1364..
2SB1000A	Si-PNP	=2SB1000:30V	39b	-	BCX51..53,2SA1213,2SA1364,2SB766A,..
2SB1000A-AK	Si-PNP	-	39	Hit	→2SB1000A
2SB1000A-AL	Si-PNP	-	39	Hit	→2SB1000A
2SB1000-AH	Si-PNP	-	39	Hit	→2SB1000
2SB1000-AJ	Si-PNP	-	39	Hit	→2SB1000
2SB1001	Si-PNP	GenP,20V,2A,150MHz	39b	Hit	2SA1314,2SA1363,2SB1121,2SB1313..
2SB1001-BH	Si-PNP	-	39	Hit	→2SB1001
2SB1001-BJ	Si-PNP	-	39	Hit	→2SB1001
2SB1002	Si-PNP	GenP,70V,1A,150MHz	39b	Hit	BCX53,2SB803..804,2SB1025..26..
2SB1002-CH	Si-PNP	-	39	Hit	→2SB1002
2SB1002-CJ	Si-PNP	-	39	Hit	→2SB1002
2SB1003	Si-P-Darl+Di	AF,Sw-Pow,60V,3A,25W,B=5000	15j$	Tos	BD716,BDW24A,BDW54A,2SB751..
2SB1004	Si-P-Darl+Di	AF,Sw-Pow,100V,4A,30W,B=4000	15j$	Tos	BDW24C,BDW54C,BDW64C,2SB751B..
2SB1005	Si-P-Darl+Di	AF,Sw-Pow,50V,4A,30W,B=3000	17j$	Sak	BD716,BDW24A,BDW54A,2SB751..
2SB1007	Si-PNP	AF-Pow,80V,0,7A,10W,100MHz	14h$	Rhm	BD140,BD231,2SA1184,2SA1220..
2SB1008	Si-PNP-Darl	AF,Sw-Pow,40V,2A,10W,150MHz,B>1000	14h$	Rhm	BD776,BD778,BD780,2SB794..795..
2SB1009	Si-PNP	AF,Sw-Pow,40V,2A,10W,100MHz	14h$	Rhm	BD376,2SB1009,2SA1217,2SB1217..
2SB101	Ge-PNP	AF,30V,0,05A,0,125W	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB1010	Si-PNP	=2SB1009:0,75W	7c(9mm)	-	2SA1315,2SA1382,2SB892,2SB1312..
2SB1011	Si-PNP	Sw,Pow,400/400V,0,1A,70MHz	14h$	Mat	2SA1156,2SA1354
2SB1012	Si-P-Darl+Di	AF,Sw-Pow,120V,1,5A,20W,B>2000	14h$	Hit	BD684
2SB1012K	Si-PNP-Darl	120V,1.5A,8W	-		-
2SB1013	Si-PNP	AF-Dr/Out,20V,2A,0,7W	7c	Sanyo	MPS750..751,2SB733,2SB738..739,2SB911
2SB1014	Si-PNP	AF-Dr/Out,60V,1A,0,7W	7c	Sanyo	BC638,BC640,2SB647,2SB910,2SB1041+
2SB1015	Si-PNP	60V,3A,25W,0.4µS	-		-
2SB1015(A)	Si-PNP	AF,Sw-Pow,60V,3A,25W,9MHz	17c	Tos	BD936F,2SA1440,2SB1094,2SB1274..
2SB1016	Si-PNP	100V,5A,30W,5MHz	-		-
2SB1016(A)	Si-PNP	AF,Sw-Pow,100V,5A,30W,5MHz	17c	Tos	BD954F,2SA1441,2SA1741,2SB1294..
2SB1017	Si-PNP	AF,Sw-Pow,80V,4A,25W,9MHz	17c	Tos	2SA1441,2SA1635,2SA1488A,2SB1335..
2SB1018	Si-PNP	100V,7A,30W,0.4µS	-		-
2SB1018(A)	Si-PNP	AF,Sw-Pow,Lo-sat,100V,7A,30W,10MHz	17c	Tos	BDX78F,2SA1442,2SA1742
2SB1019	Si-PNP	AF,Sw-Pow,Lo-sat,70V,7A,30W,10MHz	17c	Tos	BDX78F,2SA1470,2SB1097,2SB1290..
2SB102	Ge-PNP	AF-Dr/Out,30V,0,05A,0,18W	2ao	Nec	AC128K,AC153K,AC188K,2N1191..94
2SB1020(A)	Si-P-Darl+Di	AF,Sw-Pow,100V,7A,30W,B=2k..15k	17c	Tos	2SB1099,2SB1228,2SB1283
2SB1021	Si-P-Darl+Di	=2SB1020:80V	17c	Tos	2SB1099,2SB1228,2SB1283
2SB1022	Si-P-Darl+Di	=2SB1020:60V	17c	Tos	2SB1099,2SB1224,2SB1228,2SB1283..
2SB1023	Si-P-Darl+Di	AF,Sw-Pow,60V,3A,20W,B=5000	17c	Tos	2SB1223,2SB1226,2SB1257,2SB1342..
2SB1024	Si-P-Darl+Di	AF,Sw-Pow,100V,4A,30W,B=4000	17c	Tos	2SB1098,2SB1227,2SB1282,TIP127
2SB1025	Si-PNP	GenP,120/80V,1A,140MHz	39b	Hit	2SB1027..1028
2SB1025-DH	Si-PNP	-	39	Hit	→2SB1025
2SB1025-DJ	Si-PNP	-	39	Hit	→2SB1025
2SB1025-DK	Si-PNP	-	39	Hit	→2SB1025
2SB1026	Si-PNP	=2SB1025:120/100V	39b	Hit	2SB1027..1028
2SB1026-DL	Si-PNP	-	39	Hit	→2SB1025
2SB1026-DM	Si-PNP	-	39	Hit	→2SB1025
2SB1027	Si-PNP	GenP,180/120V,1,5A	39b	Hit	-
2SB1027-EH	Si-PNP	-	39	Hit	→2SB1027
2SB1027-EJ	Si-PNP	-	39	Hit	→2SB1027
2SB1027-EK	Si-PNP	-	39	Hit	→2SB1027
2SB1028	Si-PNP	=2SB1027:180/160V	39b	Hit	-
2SB1028-EL	Si-PNP	-	39	Hit	→2SB1028
2SB1028-EM	Si-PNP	-	39	Hit	→2SB1028

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2SB1029	Si-PNP	GenP,100V,2A	39b	Hit	2SA1417,2SB1027..1028
2SB103	Ge-PNP	AF-Dr/Out,30V,0,1A,0,125W	2a	Nec	AC128,AC153,AC188,2N1191..94
2SB1030	Si-PNP	=2SB643:0,3W	40c	Mat	→2SB643
2SB1030A	Si-PNP	=2SB644:0,3W	40c	-	→2SB643
2SB1031	Si-P-Darl+Di	AF,Sw-Pow,100V,15A,100W,B>1000	18j$	Hit	BDV66A,BDW84C,2SB969
2SB1032(K)	Si-P-Darl+Di	AF,Sw-Pow,120V,10A,80W,B>1000	18j$	Hit	BDV64C,BDV66B,BDW84D
2SB1033	Si-PNP	AF,Sw-Pow,60V,3A,40W	17j$	Rhm	BD242B,BD538,BD952,2SA1262..
2SB1034	Si-P-Darl+Di	AF,Sw-Pow,80V,2A,15W,50MHz,B=5000	14h$	Tos	BD680,BD780,2N6036,2SB795
2SB1035	Si-PNP	GenP,30V,1A,0,9W,100MHz	7c(9mm)	Mit	2SA966,2SB764,2SB978,2SB1041..
2SB1036	Si-PNP	=2SB788:0,3W,200MHz	40c	Mat	→2SB788
2SB1037	Si-PNP	AF-Pow,CTV-VD,150V,1,5A,30W,15MHz	17j$	Sanyo	BD240D,2SB861,2SA940,2SB628(A)..
2SB1038	Si-PNP	AF,Sw-Pow,60V,3A,30W,20MHz	15j$	Nec	BD242A,BD536,BD936,2SA1266..
2SB1039	Si-PNP	AF,Sw-Pow,100V,4A,40W,20MHz	15j$	Nec	BD244C,BD540C,BD954,2SB682..
2SB104	Ge-PNP	AF-Dr/Out,30V,0,1A,0,18W	2ao	Nec	AC128K,AC153K,AC188K,2N1191..94
2SB1040	Si-PNP	AF,Sw-Pow,20V,2A	30j$	Nec	2SA1241,2SA1243,2SB962,2SB1182..
2SB1041	Si-PNP	AF,Sw-Pow,80V,1A,0,9W	7c(9mm)	Rhm	2SA1013,2SA1275,2SB647,2SB1041
2SB1042(M)	Si-PNP	=2SB1041:1W	9c	Rhm	2SA1013,2SA1275,2SB647,2SB1041
2SB1043	Si-PNP	=2SB1041:50V	7c(9mm)	Rhm	2SB647,2SB764,2SB892,2SB1041..
2SB1044(M)	Si-PNP	=2SB1041:50V,1W	9c	Rhm	2SB647,2SB764,2SB892,2SB1041..
2SB1045	Si-PNP	GenP,120V,0,05A,140MHz	39b	Hit	2SA1173,2SA1200,2SB1046..1047
2SB1046	Si-PNP	GenP,180V,0,05A,140MHz	39b	Hit	2SB1047
2SB1047	Si-PNP	GenP,180V,0,05A,140MHz	39b	Hit	2SB1046
2SB1048	Si-PNP-Darl	GenP,60V,1A,B>2000	39b	Hit	BST60..62,2SB1126
2SB1049	Si-PNP	GenP,30V,0,1A,0,4W	9c	Mat	BC213,BC258,BC308,BC558..
2SB105	Ge-PNP	AF-Pow,30V,0,5A,0,5W	?2b$	Nec	2SB493,(AD162)
2SB1050	Si-PNP	=2SB873:	9c	Mat	→2SD873
2SB1051	Si-PNP	GenP,40V,0,3A	?35d	Rhm	BC807R,BCX17R,BCW67R..68R
2SB1051K	Si-PNP	=2SB1051:1A	35a	Rhm	-
2SB1051K-P	Si-PNP	-	35	Rhm	→2SB1051K
2SB1051K-Q	Si-PNP	-	35	Rhm	→2SB1051K
2SB1051K-R	Si-PNP	-	35	Rhm	→2SB1051K
2SB1052	Si-PNP	AF,Sw-Pow,60V,2A,25W,25MHz	17c	Mat	BD936F,2SB1187,2SB1314,2SB1375..
2SB1053	Si-PNP	GenP,40V,0,1A	35a	Mat	BC856..857,BCW69..70,BCW89..
2SB1054	Si-PNP	AF,Sw-Pow,100V,5A,60W,20MHz	16c	Mat	2SB1371..72,(BD246C,BDV96,2SB688..)
2SB1055	Si-PNP	=2SB1054:120V,6A,70W	16c	Mat	2SB1361,2SB1372,(BD246C,2SA1141..)
2SB1056	Si-PNP	=2SB1054:140V,7A,80W	16c	Mat	2SB1361,2SB1372,(BD246D,2SA1186..)
2SB1057	Si-PNP	=2SB1054:150V,9A,100W	16c	Mat	2SB1860,(BD246D,2SA1227A,2SA1386..)
2SB1058	Si-PNP	GenP,20V,2A,0,75W,80MHz	7c	Hit	MPS750,2SB733,2SB738..739,2SB892..
2SB1059	Si-PNP	GenP,70V,1A,0,75W,65MHz	7c	Hit	BC640,2SB647,2SB910,2SB984,2SB1041+
2SB106	Ge-PNP	=2SB106:3W	?2b$o	Nec	2SB493,(AD162)
2SB1060	Si-PNP	GenP,70V,1A,1W	9c	Hit	BC640,2SB647,2SB910,2SB984,2SB1041+
2SB1061	Si-PNP-Darl	Sw,Pow,300V,0,3A,15W,15MHz,B=5000	17j$	Hit,Nec	(2SB1401,2SB1465)
2SB1062	Si-PNP	GenP,15V,0,5A,0,6W,130MHz	9c	Mat	BC327..328,BC636,2SA1515,2SB909..
2SB1063	Si-PNP	=2SB1054:	17c	Mat	BD954AF,BDT42AF,2SB1016,2SB1294..
2SB1064	Si-PNP	AF,Sw-Pow,60V,3A,30W,70MHz	17j$	Rhm	BD242A,BD536,BD936,2SA1288..
2SB1065	Si-PNP	=2SB1064:10W	14h$	Rhm	BD178,BD190,BD786,2SB744(A)..
2SB1066	Si-PNP	50V,3A,1W,70MHz	-	-	-
2SB1066(M)	Si-PNP	=2SB1064:1W	9c	Rhm	2SA1707,2SA1761,2SB985,2SB1066
2SB1067	Si-P-Darl+Di	AF,Sw-Pow,80V,2A,10W,B=5000	14b	Tos	(BD680,BD780,2N6036,2SB795,..)
2SB1068	Si-PNP	GenP,20V,2A,0,75W,180MHz	7c	Nec	MPS750,2SB733,2SB738..739,2SB892..
2SB1069	Si-PNP	AF,Sw-Pow,40V,4A,25W,150MHz	17j$	Mat	2SA1012,2SA1289,2SB919
2SB1069A	Si-PNP	=2SB1069:50V	17j$	-	2SA1012,2SA1289,2SB919
2SB107	Ge-PNP	AF,Sw-Pow,30V,2A,10W	23a$	Nec	AD149,2N2137,2N2142,2SB449
2SB1070(A)	Si-PNP	=2SB1069(A):	30j$	Mat	2SB1267,(2SA1012,2SA1289,2SB919)
2SB1071	Si-PNP	40V,4A,25W,150MHz	-	-	-
2SB1071(A)	Si-PNP	=2SB1069(A):Iso	17c	Mat	2SA1307,2SA1469,2SB953(A)
2SB1072L,S	Si-P-Darl+Di	AF,Sw-Pow,100V,4A,20W,B>1000	30j$	Hit	2SB908,(BDW24C,BDW54C,2SB751B,..)
2SB1073	Si-PNP	AF,Sw,30V,4A,120MHz	39b	Mat	2SB1308,2SB1386
2SB1073-Q	Si-PNP	-	39	Mat	→2SB1073
2SB1073-R	Si-PNP	-	39	Mat	→2SB1073
2SB1074	Si-PNP	Sw,400/400V,0,5A,1W	9b	Matsushita	2SA1625,2SB1488
2SB1075	Si-PNP	AF,Sw-Pow,50V,2A,150MHz	14h$	Mat	BD376,2SB1065,2SB1217
2SB1076(M)	Si-PNP-Darl	GenP,40V,2A,1W,150MHz,B=20000	9c	Rhm	2SB1129,2SB865
2SB1077	Si-PNP-Darl	AF,Sw-Pow,60V,4A,40W,B>1000	17j$	Hit	BD716,BDW24A,BDW54A,2SB751..

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2SB1078	Si-PNP-Darl	AF,Sw-Pow,120V,8A,40W,B>1000	17j$	Hit	BD652,BDT20,BDW74D,BDX54D..
2SB1079	Si-P-Darl+Di	AF,Sw-Pow,100V,20A,100W,B>1000	18j$	Hit	2SB1383
2SB107A	Ge-PNP	=2SB107:60V	23a$	-	AD166,2N2137,2N2142
2SB108	Ge-PNP	AF-Pow,40V,0,5A,0,5W	?2b$	Nec	2SB493,(AD162)
2SB1080	Si-PNP	AF,Sw-Pow,35V,2A,10W	17m$	Hit	(BD508,BD516,BD526,BD814,..)
2SB1085	Si-PNP	AF-Pow,120V,1,5A,20W,50MHz	17j$	Rhm	BD940,2SA985(A),2SA1078,2SA1393..
2SB1085A	Si-PNP	=2SB1085:160V	17j$	-	2SA968(A,B),2SB628(A),2SA1011,2SA1332
2SB1086	Si-PNP	=2SB1085:10W	14h$	Rhm	2SA1021,2SA1249,2SB649
2SB1086A	Si-PNP	=2SB1086:160V	14h$	-	2SA1249,2SB649
2SB1087	Si-P-Darl+Di	AF,Sw-Pow,100V,5A,30W,B=8000	17j$	Nec	BD650,BD902,BDW24C,BDW64C..
2SB1088	Si-P-Darl+Di	AF,Sw-Pow,100V,±10A,60W,B=6000	15j$	Nec	BDT62B
2SB1089	Si-PNP	AF,Sw-Pow,60V,3A,30W,20MHz	17j$	Nec	BD242A,BD536,BD936.2SA1288..
2SB108A	Ge-PNP	=2SB108:60V	?2b$	-	-
2SB108B	Ge-PNP	=2SB108:80V	?2b$	-	-
2SB109	Ge-PNP	=2SB108:3W	?2b$o	Nec	2SB493,(AD162)
2SB1090	Si-PNP	AF,Sw-Pow,100V,4A,40W,20MHz	17j$	Nec	BD244A,BD536,BD950,2SA1293..
2SB1091	Si-PNP-Darl	AF,Sw-Pow,60V,8A,40W,B>1000	17j$	Hit	BD646,BD898,BDW74A,BDX54A..
2SB1092	Si-PNP-Darl	AF,Sw-Pow,80V,1,5A,8W,B=10000	14h$	Hit	BD680,BD780,2N6036,2SB795,2SB1012
2SB1093	Si-P-Darl+Di	AF,Sw-Pow,80V,±1,5A,1W,B>2000	9b	NEC	2SB678,2SB865,2SB1129,2SB1406..
2SB1094	Si-PNP	=2SB1089:Iso,15W	17c	Nec	2SA1394,2SA1488,2SB1015,2SB1274..
2SB1095	Si-PNP	=2SB1090:Iso,20W	17c	Nec	2SA1441,2SB1016,2SB1294,(BD240C,..)
2SB1096	Si-PNP	TV,AF-Pow,200V,2A,25W,5MHz	17c	Nec	(BD240F,2SA1133,2SB630,2SB720,2SB861)
2SB1097	Si-PNP	AF,Sw-Pow,Lo-sat,80V,7A,30W	17c	Nec	2SA1442,2SA1470,2SA1742,2SB1018
2SB1098	Si-P-Darl+Di	AF,Sw-Pow,100V,±5A,20W,80MHz,B=8000	17c	Nec	2SB1258,2SB1340
2SB1099	Si-P-Darl+Di	AF,Sw-Pow,100V,8A,25W,80MHz,B=6000	17c	Nec	2SB1100,2SB1284
2SB109A	Ge-PNP	=2SB108:60V,3W	?2b$o	-	-
2SB109B	Ge-PNP	=2SB108:80V,3W	?2b$o	-	-
2SB110	Ge-PNP	AF,25V,0,05A,0,1W,B>18	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1100	Si-P-Darl+Di	AF,Sw-Pow,100V,±10A,30W,80MHz,B=6000	17c	Nec	2SB1284
2SB1101	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,40W,B>1000	17j$	Hit	BD716,BD718,BDW54A..D,BDW64B..D..
2SB1102	Si-P-Darl+Di	=2SB1101:80V	17j$	Hit	BD718,BDW54B,BDW64B,2SB885..
2SB1103	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,40W,B>1000	17j$	Hit	BD646,BD898,BDW74A,BDX54A..
2SB1104	Si-P-Darl+Di	=2SB1103:80V	17j$	Hit	BD648,BD900,BDW74B,BDX54B..
2SB1105	Si-P-Darl+Di	AF,Sw-Pow,120V,3A,30W,B>1000	17j$	Hit	BDT60C,BDW54D,2SB1339
2SB1106	Si-P-Darl+Di	AF,Sw-Pow,120V,6A,40W,B>1000	17j$	Hit	BD652,BDT20,BDW64D,2SB1339..
2SB1107	Si-P-Darl+Di	AF,Sw-Pow,120V,10A,40W,B=5000	17j	Hit	BDT62C,BDX34D
2SB1108	Si-PNP-Darl	AF,Sw-Pow,120V,8A,50W,30MHz,B>1000	17c	Mat	BD652F,BDT62CF,2SB1259,2SB1107
2SB1109	Si-PNP	AF/Vid-Pow,160V,0,1A,140MHz	14h$	Hit	BF416,BF418,2SA1352..1353,2SA1380
2SB1109S	Si-PNP	160V,0.1A,1.25W	-		-
2SB111	Ge-PNP	=2SB110:a>30	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1110	Si-PNP	=2SB1109:200/200V	14h$	Hit	BF416,BF418,2SA1352..1353,2SA1380
2SB1111	Si-P-Darl+Di	2A,10W,B>2000	14h$	Nec	2SB794..795,2SB1012
2SB1112	Si-P-Darl+Di	120V,6A,40W,B=5000	15j$	Hit	BDT20,BD652,BDW64D,2SB1339..
2SB1113	Si-P-Darl+Di	120V,8A,40W,B=5000	15j$	Hit	BDT20,BD652,BDW74D,2SB1107..
2SB1114	Si-PNP	GenP,20V,2A,180MHz	39b	Nec	2SA1203,2SA1213,2SA1314,2SA1369
2SB1114-ZK	Si-PNP	-	39	Nec	→2SB1114
2SB1114-ZL	Si-PNP	-	39	Nec	→2SB1114
2SB1114-ZM	Si-PNP	-	39	Nec	→2SB1114
2SB1115	Si-PNP	GenP,Lo-sat,60V,1A,>80MHz	39b	Nec	2SA1364,2SB1122..23,2SB1520
2SB1115A	Si-PNP	=2SB1115:80V	39b	Nec	2SB1520
2SB1115A-YP	Si-PNP	-	39	Nec	→2SB1115A
2SB1115A-YQ	Si-PNP	-	39	Nec	→2SB1115A
2SB1115-YK	Si-PNP	-	39	Nec	→2SB1115
2SB1115-YL	Si-PNP	-	39	Nec	→2SB1115
2SB1115-YM	Si-PNP	-	39	Nec	→2SB1115
2SB1116	Si-PNP	GenP,Lo-sat,60V,1A,0,75W,120MHz	7c	Nec	2SA1315,2SA1706,2SB892,2SB1229..
2SB1116A	Si-PNP	=2SB1116:80V	7c	-	2SA1315,2SA1708..09,2SB1459
2SB1117	Si-PNP	AF-Pow,Lo-sat,30V,3A,1W,280MHz	9b	NEC	2SB985,2SB1505
2SB1118	Si-PNP	Lo-sat,20V,0,7A,250MHz	39b	Sanyo	2SA1734,(BC869,BCX51..53,BCX69..)
2SB1119	Si-PNP	AF,25V,1A,180MHz	39b	Sanyo	BC869,BCX51..53,BCX69,2SA1314..
2SB112	Ge-PNP	=2SB110:a>43	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1120	Si-PNP	Lo-sat,20V,2,5A,250MHz	39b	Sanyo	2SB1301,2SB1518
2SB1121	Si-PNP	Lo-sat,30V,2A,150MHz	39b	Sanyo	2SA1681,2SB1313..14,2SB1518
2SB1121T	Si-PNP	30V,2A,150MHz	-		-

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2SB1122	Si-PNP	AF,Lo-sat,60V,1A,150MHz	39b	Sanyo	2SA1364,2SB1115(A),(BCX52..53,..)
2SB1123	Si-PNP	Sw,Lo-sat,60V,2A,150MHz	39b	Sanyo	2SA1681,2SB1520,(2SA1417,2SB1029)
2SB1124	Si-PNP	Sw,Lo-sat,60V,3A,150MHz	39b	Sanyo	2SA1736,2SB1572
2SB1125	Si-PNP-Darl	80V,0,7A,170MHz,B>5000	39b	Sanyo	BST61..62
2SB1126	Si-PNP-Darl	80V,1,5A,120MHz,B>4000	39b	Sanyo	-
2SB1127	Si-PNP	Strobo,Lo-sat,25V,5A,10W,320MHz	14h$	Sanyo	2SA1120,2SA1357
2SB1128	Si-P-Darl+Di	AF,Sw-Pow,50V,2A,10W,B=5000	14b	Tos	-
2SB1129	Si-PNP-Darl	AF,Sw,80V,±1,5A,1W,B=10000	9b	NEC	2SB865
2SB113	Ge-PNP	=2SB110:a>61	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1130(M)	Si-PNP	AF-Out,120V,1,5A,1W,50MHz	9c	Rhm	2SB1212,2SB1236
2SB1130A(M)	Si-PNP	=2SB1130:160V	9c	-	2SA1770,2SB1212,2SB1236A
2SB1131	Si-PNP	=2SB1127:1W	7c(9mm)	Say,Rhm	2SB1288,2SB1306
2SB1132	Si-PNP	AF-Pow,40V,1A,150MHz	39b	Rhm	BCX51..53,2SA1364,2SB766A,2SB1123,..
2SB1132-P	Si-PNP	-	39	Rhm	→2SB1132
2SB1132-Q	Si-PNP	-	39	Rhm	→2SB1132
2SB1132-R	Si-PNP	-	39	Rhm	→2SB1132
2SB1133	Si-PNP	AF-Pow,60V,3A,25W,40MHz	17c	Sanyo	2SA1635,2SA1488,2SB1094,2SB1274..
2SB1134	Si-PNP	Sw,Pow,Lo-sat,60V,5A,25W,30MHz	17c	Sanyo	2SA1307,2SA1441,2SA1469,2SB1019..
2SB1135	Si-PNP	Sw,Pow,Lo-sat,60V,7A,30W,10MHz	17c	Sanyo	2SA1442,2SA1470,2SB1018..19
2SB1136	Si-PNP	Sw,Pow,Lo-sat,60V,12A,30W,10MHz	17c	Sanyo	2SA1451..52,2SA1568,2SB1468
2SB1137	Si-P-Darl+Di	Sw,Pow,100V,10A,65W,B=6000	18c	Nec	2SB1388
2SB114	Ge-PNP	AF,25V,0,05A,0,1W,B>45	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1140	Si-PNP	=2SB1127:Iso	14b	Sanyo	2SA1357
2SB1141	Si-PNP	AF,Sw-Pow,Lo-sat,20V,1,2A,10W,150MHz	14b	Sanyo	2SA1359,2SB891,(BD136,BD166,BD227)
2SB1142	Si-PNP	Sw,Pow,Lo-sat,60V,2,5A,10W,140MHz	14b	Sanyo	(BD178,BD188,BD440,2N5194,..)
2SB1143	Si-PNP	AF,Sw-Pow,Lo-sat,60V,4A,10W,150MHz	14b	Sanyo	(BD188,BD440,BD786,2SB986,..)
2SB1144	Si-PNP	AF,Sw-Pow,Lo-sat,120V,1,5A,40W,100MHz	14b	Sanyo	2SA1408,2SA1507,(2SA1021,2SA1249)
2SB1145	Si-P-Darl+Di	AF,Sw-Pow,120V,3A,20W,B=5000	15c	Hit	BDT60CF,2SB1340
2SB1146	Si-P-Darl+Di	AF,Sw-Pow,120V,6A,25W,B=5000	15c	Hit	BD652F,2SB1340,2SB1259
2SB1147	Si-P-Darl+Di	AF,Sw-Pow,120V,8A,25W,B=5000	15c	Hit	BD652F,2SB1259
2SB1148(A)	Si-PNP	=2SB936(A):15W	?30j$	Mat	-
2SB1149	Si-P-Darl+Di	AF,Sw-Pow,100V,±3A,15W,B=10000	14h$	Nec	-
2SB115	Ge-PNP	=2SB114:B>60	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1150	Si-P-Darl+Di	AF,Sw-Pow,Int.Z-Di,60V,3A,15W,B=10000	14h$	Nec	-
2SB1151	Si-PNP	Lo-sat,60V,5A,20W,<1/3,5µS	14h$	Nec	-
2SB1152	Si-PNP	AF,Sw-Pow,160V,12A,120W	18j$	Mat	BD746F,2SA1386(A),2SA1516,2SB817,..
2SB1153	Si-PNP	AF,Sw-Pow,170V,15A,150W	77j$	Mat	2SA1302,2SA1553,2SB1163
2SB1154	Si-PNP	AF,Sw-Pow,130V,10A,70W,30MHz	16c	Mat	2SA1672,2SA1805,(BD246D,2SA1146,..)
2SB1155	Si-PNP	AF,Sw-Pow,130V,15A,80W,25MHz	16c	Mat	2SB1860,(BD746D,2SA1227,2SA1386,..)
2SB1156	Si-PNP	AF,Sw-Pow,130V,20A,100W,25MHz	16c	Mat	(BD250D,BD746D)
2SB1157	Si-PNP	AF,Sw-Pow,100V,5A,60W,20MHz	16c	Mat	2SB1371..72,(BD246C,BDV96,2SA1141,..)
2SB1158	Si-PNP	AF,Sw-Pow,120V,6A,70W,20MHz	16c	Mat	2SB1371..72,(BD246D,2SA1146,2SA1186)
2SB1159	Si-PNP	AF,Sw-Pow,140V,7A,100W,20MHz	16c	Mat	2SB1361,(BD246D,2SA1146,2SA1186,..)
2SB116	Ge-PNP	=2SB114:B>80	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1160	Si-PNP	AF,Sw-Pow,150V,9A,100W,20MHz	16c	Mat	(BD246D,2SA1186,2SA1227,2SA1386,..)
2SB1161	Si-PNP	AF,Sw-Pow,160V,12A,120W,20MHz	16c	Mat	2SA1673,(BD746F,2SA1386,2SB817,..)
2SB1162	Si-PNP	=2SB1161:	77j$	Mat	2SA1301..1302,2SB1153,2SB1347
2SB1163	Si-PNP	AF,Sw-Pow,180V,15A,150W,20MHz	77j$	Mat	2SA1302,2SA1553,2SB1429
2SB1164	Si-PNP	AF-Pow,60V,2A,1W	9b	NEC	MPS750..751,2SA1315,2SA1429,2SB892
2SB1165	Si-PNP	Sw,Pow,Lo-sat,60V,5A,20W,130MHz	?14h$	Sanyo	-
2SB1166	Si-PNP	Sw,Pow,Lo-sat,60V,8A,20W,130MHz	?14h$	Sanyo	-
2SB1167	Si-PNP	Sw,Pow,Lo-sat,120V,3A,20W,130MHz	?14h$	Sanyo	-
2SB1168	Si-PNP	Sw,Pow,Lo-sat,120V,4A,20W,130MHz	?14h$	Sanyo	-
2SB1169(A)	Si-PNP	=2SB954(A):15W	?30j$	Mat	2SB839,2SB957..958,2SB1201
2SB117	Ge-PNP	=2SB114:B>105	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB1170	Si-PNP	=2SB1052:15W	?30j$	Mat	2SB839,2SB957..958,2SB1201
2SB1171(A)	Si-PNP	=2SB928(A):15W	?30j$	Mat	2SB768,(2SB928(A))
2SB1172(A)	Si-PNP	=2SB929(A):15W	?30j$	Mat	2SB906,2SB1184,2SB1202
2SB1173(A)	Si-PNP	=2SB930(A):15W	?30j$	Mat	2SA1395,2SA1401,2SB1203,2SB1244
2SB1174	Si-PNP	=2SB931:15W	?30j$	Mat	-
2SB1175	Si-PNP	=2SB932:15W	?30j$	Mat	-
2SB1176	Si-PNP	=2SB933:15W	?30j$	Mat	-
2SB1177	Si-PNP	=2SB934:15W	?30j$	Mat	-
2SB1178(A)	Si-P-Darl+Di	=2SB937(A):15W	?30j$	Mat	2SB907,2SB1214

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2SB1179(A)	Si-P-Darl+Di	=2SB938(A): 15W	?30j$	Mat	-
2SB118	Ge-PNP	AF, Sw-Pow, 15V, 1,5A, 50W	23a$	Mat	AD149, 2N2137, 2N2142, 2SB449..
2SB1180(A)	Si-P-Darl+Di	=2SB939(A): 15W	?30j$	Mat	-
2SB1181(FS)	Si-PNP	AF-Out/Pow, 80V, 1A, 10W, 100MHz	30j$	Rhm	2SB839, 2SB957..958
2SB1182	Si-PNP	40V, 2A, 10W, 100MHz	-		-
2SB1182(FS)	Si-PNP	AF-Out/Pow,	30j$	Rhm	2SA1241, 2SB838, 2SB1201
2SB1183(FS)	Si-PNP-Darl	AF-Out/Pow, 40V, 2A, 10W, B>1000	30j$	Rhm	2SB907, 2SB1214
2SB1184	Si-PNP	60V, 3A, 15W, 70MHz	-		-
2SB1184(FS)	Si-PNP	AF-Out/Pow, 60V, 3A, 15W, 70Mhz	30j$	Rhm	2SA1876, 2SB906, 2SB1202
2SB1185	Si-PNP	=2SB1184: 25W	17c	Rhm	2SA1307, 2SA1440, 2SA1469, 2SB1274
2SB1186	Si-PNP	AF-Out, 120V, 1,5A, 20W, 50MHz	17c	Rhm	2SA1306, 2SA1332, 2SA1393, 2SA1606..
2SB1186A	Si-PNP	=2SB1186: 160V	17c	-	2SA1306(A,B), 2SA1332, 2SA1606
2SB1187	Si-PNP	AF-Out/Pow, 60V, 3A, 30W, 12MHz	17c	Rhm	2SA1440, 2SA1469, 2SB1015, 2SB1094..
2SB1188	Si-PNP	AF, 40V, 2A, 100MHz	39b	Rhm	2SA1213, 2SB1123
2SB1188-P	Si-PNP	AF, 40V, 2A, 100MHz	39	Rhm	→2SB1188
2SB1188-Q	Si-PNP	AF, 40V, 2A, 100MHz	39	Rhm	→2SB1188
2SB1188-R	Si-PNP	AF, 40V, 2A, 100MHz	39	Rhm	→2SB1188
2SB1189	Si-PNP	AF, 80V, 0,7A, 100MHz	39b	Rhm	BCX53, 2SB803..805, 2SB1025..1026
2SB1189-P	Si-PNP	AF, 80V, 0,7A, 100MHz	39	Rhm	→2SB1189
2SB1189-Q	Si-PNP	AF, 80V, 0,7A, 100MHz	39	Rhm	→2SB1189
2SB1189-R	Si-PNP	AF, 80V, 0,7A, 100MHz	39	Rhm	→2SB1189
2SB119	Ge-PNP	=2SB118: 32V	23a$	Mat	AD149, 2N2137, 2N2142, 2SB449..
2SB1190	Si-PNP	AF-Pow, 200/150V, 1A, 25W, 20MHz	17j$	Mat	BD240F, 2SB630, 2SA968B, 2SB861
2SB1190A	Si-PNP	=2SB1190: 200/180V	17j$	-	BD240F, 2SB630, 2SA968B, 2SB861
2SB1191(A)	Si-PNP	=2SB1190(A):	30j$	Mat	2SB928, (2SB630, 2SA968B, 2SB861)
2SB1192(A)	Si-PNP	=2SB1190(A):	17c	Mat	2SA1306B, 2SA1668, 2SB1096, 2SB1530
2SB1193	Si-PNP-Darl	AF-Pow, 120V, 8A, 50W, 15MHz, B>1000	17c	Mat	BD652F, BDT62CF, 2SB1259
2SB1194	Si-PNP-Darl	AF-Pow, 100V, 5A, 30W, 30MHz, B>1500	17c	Mat	2SB1098, 2SB1227, 2SB1258, 2SB1340
2SB1195	Si-PNP-Darl	AF-Pow, 100V, 8A, 50W, B=5000	17c	Mat	2SB1099..1100, 2SB1284
2SB1196	Si-PNP	AF-Pow, 70V, 4A, 25W	15c	Hit	2SA1394, 2SA1469, 2SB1019, 2SB1095..
2SB1197K	Si-PNP	AF, 40V, 0,8A, 200MHz	35a	Rhm	BCW67..68
2SB1197K-P	Si-PNP	-	35	Rhm	→2SB1197K
2SB1197K-Q	Si-PNP	-	35	Rhm	→2SB1197K
2SB1197K-R	Si-PNP	-	35	Rhm	→2SB1197K
2SB1198K	Si-PNP	AF, 80V, 0,5A, 180MHz	35a	Rhm	BCX42
2SB1198K-P	Si-PNP	-	35	Rhm	→2SB1198K
2SB1198K-Q	Si-PNP	-	35	Rhm	→2SB1198K
2SB1198K-R	Si-PNP	-	35	Rhm	→2SB1198K
2SB1199	Si-PNP	AF, 15V, 1A, 0,3W	9c	Rhm	BC327..328, 2SA1515
2SB119A	Ge-PNP	=2SB118: 60V	23a$	-	AD166..167, 2N2139, 2N2144..
2SB12	Ge-PNP	AF, 30V, 0,05A, 0,05W	5g	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB120	Ge-PNP	AF, 32V, 0,02A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB1201	Si-PNP	Sw, Pow, Lo-sat, 60V, 2A, 15W, 150MHz	30j$	Sanyo	-
2SB1202	Si-PNP	Sw, Pow, Lo-sat, 60V, 3A, 15W, 150MHz	30j$	Sanyo	2SA1244
2SB1203	Si-PNP	Sw, Pow, Lo-sat, 60V, 5A, 20W, 130MHz	30j$	Sanyo	2SA1244
2SB1204	Si-PNP	Sw, Pow, Lo-sat, 60V, 8A, 20W, 130MHz	30j$	Sanyo	-
2SB1205	Si-PNP	Sw, Pow, Lo-sat, 25V, 5A, 10W, 320MHz	30j$	Sanyo	-
2SB1206	Si-PNP	=2SB774: 0,3W	40c	Mat	→2SB774
2SB1207	Si-PNP	GenP, 15V, 0,5A, 0,3W, 130MHz	40c	Mat	BC327..328, BC636, 2SA1515, 2SB909..
2SB1208	Si-PNP	R2=10kΩ, AF, 20V, 2A, 120MHz	39b	Mat	(2SA1213, 2SA1314, 2SA1363, 2SB1121..)
2SB1209	Si-PNP	AF, Sw, 400/400V, 0,1A, 1W, 50MHz	9c	Mat	2SA1363, 2SA1372, 2SA1584, 2SA1760
2SB121	Ge-PNP	AF, Sw, 105V, 0,1A, 0,05W	2a	Fui	ACY39, 2N4042..4043
2SB1210	Si-PNP	AF, 20V, 2A, 0,5W, 80MHz	7c	Rhm	MPS750, 2SB733, 2SB738..739, 2SB892..
2SB1211	Si-PNP	=2SB1210: SMD	39b	Rhm	2SA1213, 2SA1314, 2SA1363, 2SB1121..
2SB1212	Si-PNP	AF, 160V, 1,5A, 0,9W, 50MHz	7c(9mm)	Rhm	2SA1770, 2SB1130A, 2SB1236A
2SB1213	Si-P-Darl+Di	AF, Sw-Pow, 120V, 10A, 30W, B=5000	15c	Hit	BDT62CF, 2SB1259
2SB1214	Si-P-Darl+Di	AF, Sw-Pow, 80V, 3A, 15W, B=5000	30j$	Sanyo	2SB908, 2SB1072, 2SB1303
2SB1215	Si-PNP	Sw, Pow, Lo-sat, 120V, 3A, 20W, 130MHz	30j$	Sanyo	2SA1647
2SB1216	Si-PNP	Sw, Pow, Lo-sat, 120V, 4A, 20W, 130MHz	30j$	Sanyo	2SA1647
2SB1217	Si-PNP	AF, Sw-Pow, Lo-sat, 60V, 3A, 10W, 50MHz	14h$	Nec	2SB986
2SB1218	Si-PNP	=2SB709:	35a(2mm)	Mat	2SA1576, 2SA1586, 2SA1603, 2SA1622
2SB1218A	Si-PNP	-	35(2mm)	Mat	→2SB1218A
2SB1218A-Q	Si-PNP	-	35(2mm)	Mat	→2SB1218A
2SB1218A-R	Si-PNP	-	35(2mm)	Mat	→2SB1218A

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2SB1218A-S	Si-PNP	-	35(2mm)	Mat	→2SB1218A
2SB1218-Q	Si-PNP	-	35(2mm)	Mat	→2SB1218
2SB1218-R	Si-PNP	-	35(2mm)	Mat	→2SB1218
2SB1218-S	Si-PNP	-	35(2mm)	Mat	→2SB1218
2SB1219	Si-PNP	-	35(2mm)	Mat	→2SB1219
2SB1219A	Si-PNP	-	35(2mm)	Mat	→2SB1219A
2SB1219A-Q	Si-PNP	-	35(2mm)	Mat	→2SB1219A
2SB1219A-R	Si-PNP	-	35(2mm)	Mat	→2SB1219A
2SB1219A-S	Si-PNP	-	35(2mm)	Mat	→2SB1219A
2SB1219-Q	Si-PNP	-	35(2mm)	Mat	→2SB1219
2SB1219-R	Si-PNP	-	35(2mm)	Mat	→2SB1219
2SB1219-S	Si-PNP	-	35(2mm)	Mat	→2SB1219
2SB122	Ge-PNP	AF,Sw-Pow,80V,1,5A,20W	23a$	Tos	AD167,2N2141,2N2146
2SB1220	Si-PNP	-	35(2mm)	Mat	→2SB1220
2SB1220-Q	Si-PNP	-	35(2mm)	Mat	→2SB1220
2SB1220-R	Si-PNP	-	35(2mm)	Mat	→2SB1220
2SB1220-S	Si-PNP	-	35(2mm)	Mat	→2SB1220
2SB1220-T	Si-PNP	-	35(2mm)	Mat	→2SB1220
2SB1221	Si-PNP	Vid,250/200V,0,07A,1W,80MHz	7c(9mm)	Mat	BF423A,BF436,BF492,2SA1371..72..
2SB1222	Si-PNP	Sw,40V,0,2A,-/<300nS	35a	Mat	BSR15..16,BSR18,2SA1338
2SB1223	Si-P-Darl+Di	AF,Sw-Pow,70V,4A,20W,20MHz,B=5000	17c	Sanyo	2SB1024,2SB1098,2SB1282,2SB1342..
2SB1224	Si-P-Darl+Di	AF,Sw-Pow,70V,7A,25W,20MHz,B=5000	17c	Sanyo	2SB1021,2SB1099,2SB1228,2SB1283..
2SB1225	Si-P-Darl+Di	AF,Sw-Pow,70V,10A,30W,20MHz,B=5000	17c	Sanyo	2SB1100,2SB1259,2SB1284
2SB1226	Si-P-Darl+Di	AF,Sw-Pow,110V,3A,20W,20MHz,B=4000	17c	Sanyo	BDT60CF,2SB1340
2SB1227	Si-P-Darl+Di	AF,Sw-Pow,110V,5A,25W,20MHz,B=4000	17c	Sanyo	2SB1340,2SB1344
2SB1228	Si-P-Darl+Di	AF,Sw-Pow,110V,8A,30W,20MHz,B=4000	17c	Sanyo	2SB1193,2SB1259,2SB1344
2SB1229	Si-PNP	Sw,Lo-sat,60V,2A,0,75W,150MHz	7c	Sanyo	2SA1706,2SB892,2SB1312,2SB1433..
2SB123	Ge-PNP	AF,Sw-Pow,40V,5A,20W	23a$	Tos	AD166..167,2N1529..38,2N1539..48..
2SB1230	Si-PNP	AF,Sw-Pow,Lo-sat,110V,15A,100W	18j$	Sanyo	-
2SB1231	Si-PNP	AF,Sw-Pow,Lo-sat,110V,25A,120W	18j$	Sanyo	-
2SB1232	Si-PNP	AF,Sw-Pow,Lo-sat,110V,40A,150W	18j$	Sanyo	-
2SB1233(A)	Si-PNP	=2SB1192(A):15W	?30j$	Mat	2SB768,2SB842,(2SB928(A))
2SB1234	Si-PNP	-	35	Sanyo	→2SB1234
2SB1235	Si-PNP-Darl	AF,80V,0,2A,B>5000	40c	Sanyo	-
2SB1236	Si-PNP	=2SB1130,A(M,AM):Pins=14mm	9c	Rhm	→2SB1130..
2SB1237	Si-PNP	=2SB909:Pins=14mm	9c	Rhm	→2SB909
2SB1238	Si-PNP	=2SB910:Pins=14mm	9c	Rhm	→2SB910
2SB1239	Si-PNP-Darl	=2SB1076(M):Pins=14mm	9c	Rhm	→2SB1076
2SB124	Ge-PNP	Sw,Pow,60V,15A,40W	-	Tos	(2N1550..52,2N1554..56,2N1558..60,..)
2SB1240	Si-PNP	=2SB911:Pins=14mm	9c	Rhm	→2SB911
2SB1241	Si-PNP	GenP,80V,1A,1W,100MHz	9c	Rhm	BC640,BCX23,BCX39,2SB647..
2SB1242	Si-PNP	GenP,50V,1A,1W	9c	Rhm	BC327,BC638,BC640,2SB647..
2SB1243	Si-PNP	=2SB1184:	9c	Rhm	→2SB1066M
2SB1244	Si-PNP	Vid,160/160V,0,1A,0,9W,140MHz	7c(9mm)	Hit	BF423A,BF435,BF491,2SA1370..72..
2SB1245	Si-PNP	=2SB1244:200/200V	7c(9mm)	Hit	BF423A,BF436,BF491,2SA1370..73..
2SB1246	Si-PNP	AF,Sw-Pow,40V,2A,10W	30j$	Mit	2SA1241,2SB838,2SB1182,2SB1201..
2SB1247	Si-PNP	AF,Sw-Pow,60V,1,5A,10W	30j$	Mit	2SB839,2SB957..960,2SB1201..02..
2SB1248	Si-PNP	AF,Sw-Pow,110V,0,8A,10W	30j$	Mit	2SA1592,2SB844..845,2SB959..960..
2SB1249	Si-PNP	AF,Sw-Pow,130V,0,8A,10W	30j$	Mit	2SA1225,2SB840..842,2SB905,2SB1275,..
2SB125	Ge-PNP	=2SB124:36V	-	Tos	(2N1549..52,2N1553..56,2N1557..60,..)
2SB1250	Si-PNP-Darl	AF,Sw-Pow,100V,3A,35W,20MHz,B>5000	17c	Mat	2SB1098,2SB1251..52,2SB1430
2SB1251	Si-PNP-Darl	AF,Sw-Pow,110V,4A,40W,20MHz,B>5000	17c	Mat	2SB1098,2SB1252,2SB1430
2SB1252	Si-PNP-Darl	AF,Sw-Pow,120V,5A,45W,20MHz,B>5000	17c	Mat	-
2SB1253	Si-PNP-Darl	AF,Sw-Pow,130V,6A,50W,20MHz,B>5000	16c	Mat	2SB1254..55,2SB1587..88
2SB1254	Si-PNP-Darl	AF,Sw-Pow,160V,7A,70W,20MHz,B>5000	16c	Mat	2SB1255,2SB1587..88
2SB1255	Si-PNP-Darl	AF,Sw-Pow,160V,8A,100W,20MHz,B>5000	16c	Mat	2SB1588
2SB1256	Si-P-Darl+Di	AF,Sw,100V,2A,1,2W,B=2000	7c(9mm)	Rhm	2SB1387,2SB1318
2SB1257	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,25W,200MHz,B>2000	17c	Sak	2SB1282,(2SB1098,2SB1223,2SB1342,..)
2SB1258	Si-P-Darl+Di	AF,Sw-Pow,100V,6A,30W,100MHz,B>1000	17c	Sak	2SB1283,(2SB1099,2SB1228,2SB1340,..)
2SB1259	Si-P-Darl+Di	AF,Sw-Pow,120V,10A,30W,B>2000	17c	Sak	BDT62CF,BDT64CF
2SB126	Ge-PNP	AF,Sw-Pow,32V,3,5A,30W	23a$	Mat	AD149,AD166..167,AL102..103..
2SB1260	Si-PNP	AF,80V,1A,100MHz	39b	Rhm	BCX53,2SB803..804,2SB1025..1026
2SB1260-P	Si-PNP	-	39	Rhm	→2SB1260
2SB1260-Q	Si-PNP	-	39	Rhm	→2SB1260

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2SB1260-R	Si-PNP	-	39	Rhm	→2SB1260
2SB1261(Z)	Si-PNP	AF,Sw-Pow,60V,3A,10W,50MHz,<0,5/2,5μS	30j$	Nec	2SB906,2SB1184,2SB1202
2SB1262	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,25W,B=5000	15c	Hit	2SB1257,2SB1223,2SB1342
2SB1263	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,25W,B=5000	15c	Hit	2SB1020..21,2SB1099,2SB1224
2SB1264	Si-PNP	=2SB1221:0,6W	9c	Mat	BF423A,BF436..437,2SA1371..
2SB1265	Si-PNP	AF,400/400V,0,1A,1W	9c	Mat	2SA1024,2SA1372,2SA1251,2SB1209..
2SB1266	Si-PNP	AF,Sw-Pow,60V,3A,30W,8MHz	30j$	Sanyo	2SB929..930(A),(BD936,BD540A,..)
2SB1267	Si-PNP	Sw,Pow,Lo-sat,60V,8A,30W,120MHz	30j$	Sanyo	-
2SB1268	Si-PNP	Sw,Pow,Lo-sat,60V,5A,30W,30MHz	30j$	Sanyo	2SB1270,2SB1449,2SB1451
2SB1269	Si-PNP	Sw,Pow,Lo-sat,60V,7A,40W,10MHz	30j$	Sanyo	2SB1271,2SB1450,2SB1452
2SB126A	Ge-PNP	=2SB126:60V	23a$	-	AD166..167,AL102..103,2SB231..
2SB127	Ge-PNP	AF,Sw-Pow,32V,3,5A,30W	23a$	Mat	AD149,AD166..167,AL102..103..
2SB1270	Si-PNP	Sw,Pow,Lo-sat,90V,5A,30W,20MHz	30j$	Sanyo	2SB1451..52
2SB1271	Si-PNP	Sw,Pow,Lo-sat,90V,7A,40W,20MHz	30j$	Sanyo	2SB1452
2SB1272	Si-P-Darl+Di	AF,Sw-Pow,100V,2A,10W,B>1000	14h$	Rhm	BD682,2SB1012
2SB1273	Si-PNP	AF-Pow,60V,3A,30W,100MHz	17j$	Sanyo	2SA1012,2SA1288,2SA1293,2SB1064
2SB1274	Si-PNP	=2SB1273:Iso,20W	17c	Sanyo	2SA1307,2SA1440,2SA1469,2SB1185
2SB1275(F5)	Si-PNP	AF,Sw-Pow,160V,1,5A,10W,50MHz	30j$	Rhm	2SA1225,2SA1552,2SB840..842..
2SB1276	Si-PNP	=2SB737:Pins=14mm	9c	Rhm	→2SB737
2SB1277	Si-PNP	=2SB822:Pins=14mm	9c	Rhm	→2SB822
2SB1278	Si-PNP	=2SB851:Pins=14mm	9c	Rhm	→2SB851
2SB1279	Si-PNP	AF,15V,0,2A,0,3W	9c	Rhm	BC213,BC258,BC308,BC558,2SA1515+
2SB127A	Ge-PNP	=2SB127:60V	23a$	-	AD166..167,AL102..103,2SB231..
2SB128	Ge-PNP	AF,Sw-Pow,80V,6A,30W	23a$	Mat	AL102..103,2N3615..3618
2SB1280	Si-P-Darl+Dl	AF,Sw-Pow,120V,3A,25W,B=5000	15c	Hit	2SB1252,2SB1340
2SB1281	Si-P-Darl+Di	AF,Sw-Pow,120V,6A,25W,B=5000	15c	Hit	2SB1193,2SB1340
2SB1282	Si-P-Darl+Di	AF,Sw-Pow,100V,±4A,25W,50MHz,B>1500	15c	Shi	BDT60BF,2SB1024,2SB1194,2SB1381..
2SB1283	Si-PNP-Darl	AF,Sw-Pow,100V,7A,30W,50MHz,B>1500	15c	Shi	BD650F,2SB1020,2SB1099,2SB1431..
2SB1284	Si-PNP-Darl	AF,Sw-Pow,100V,10A,35W,50MHz,B>1500	15c	Shi	2SB1100,2SB1259,2SB1432
2SB1285	Si-PNP-Darl	AF,Sw-Pow,100V,15A,100W,50MHz,B>1500	16j$	Shi	BDV66A..D,BDW84C..D
2SB1286	Si-P-Darl+Di	AF,Sw-Pow,100V,2A,25W,B>1000	17j$	Rhm	BDW24C,BDW54C,BDW64C,2SB751B..
2SB1287	Si-P-Darl+Di	=2SB1286:Iso,20W	17c	Rhm	2SB1024,2SB1098,2SB1282
2SB1288	Si-PNP	DC-DC Converter,30V,5A,1W,120MHz	7c(9mm)	Mat	2SB1306,2SB1319,2SB1398
2SB1289	Si-PNP	AF,Sw-Pow,80V,7A,40W,12MHz	17j$	Rhm	BD544C,BD712,BD802,2SB870..
2SB128A	Ge-PNP	=2SB128:120V	23a$	-	AL100,AL102,2N2290,2N2293
2SB129	Ge-PNP	AF,Sw-Pow,80V,6A,30W	23a$	Mat	AL102..103,2N3615..3618
2SB1290	Si-PNP	=2SB1289:Iso,30W	17c	Rhm	2SA1396,2SA1442,2SA1651,2SB1018
2SB1291	Si-PNP	AF-Pow,60V,5A,40W,12MHz	17j$	Rhm	BD244B,BD544B,BD952,2SA1012..
2SB1292	Si-PNP	=2SB1291:Iso,30W	17c	Rhm	BD950F,2SA1394,2SA1469,2SB1097,..
2SB1293	Si-PNP	=2SB1291:100V	17j$	Rhm	BD244C,BD544C,BD954,2SB633..
2SB1294	Si-PNP	=2SB1291:Iso,100V,30W	17c	Rhm	BD954F,2SA1388,2SA1441,2SB1016,..
2SB1295	Si-PNP	-	35	Sanyo	→2SB1295
2SB1296	Si-PNP	AF,Lo-sat,15V,0,8A,0,3W,300MHz	40c	Sanyo	2SA1705,2SB1116,(BC327..328,..)
2SB1297	Si-PNP	AF,120V,0,5A,1W,250MHz	7c(9mm)	Mat	2SA840,2SA965,2SB647,2SB987..
2SB1298	Si-PNP	AF,40V,2A,1,2W	7c(9mm)	Rhm	2SA1315,2SA1382,2SB892,2SB1312..
2SB1299	Si-PNP	Hi-beta,80V,3A,40W,30MHz,B>300	17c	Mat	-
2SB129A	Ge-PNP	=2SB129:120V	23a$	-	AL100,AL102,2N2290,2N2293
2SB13	Ge-PNP	AF,30V,0,05A,0,05W	5g	Ful	AC125..126,AC151,2SB54,2SB56
2SB130	Ge-PNP	AF,Sw-Pow,32V,1,5A,6,5W	22a$	Mat	AD162,2SB474
2SB1300	Si-PNP	AF,Sw,Lo-sat,20V,3A,0,75W,140MHz	7c	Nec	2SB893,2SB985,2SB1117,2SB1505..
2SB1301	Si-PNP	=2SB1300:SMD	39b	Nec	2SA1736,2SB1124,2SB1518
2SB1301-ZP	Si-PNP	-	39	Nec	→2SB1301
2SB1301-ZQ	Si-PNP	-	39	Nec	→2SB1301
2SB1301-ZR	Si-PNP	-	39	Nec	→2SB1301
2SB1302	Si-PNP	Sw,Lo-sat,25V,5A,320MHz	39b	Sanyo	(2SB1073)
2SB1303	Si-P-Darl+Di	AF,Sw-Pow,110V,3A,10W,20MHz,B>1500	30j$	Sanyo	2SB908,2SB1072
2SB1304	Si-PNP	AF,Sw-Pow,100V,4A,20W	15c	Hit	2SA1441,2SB1016,2SB1095,2SB1294..
2SB1305	Si-PNP	AF,30V,5A,0,75W,120MHz	7c	Rhm	2SB1050,2SB1288,2SB1326,2SB1398..
2SB1306	Si-PNP	=2SB1305:1,2W	7c(9mm)	Rhm	2SB1288,2SB1446
2SB1307(M)	Si-PNP	=2SB1305:0,3W	9c	Rhm	2SB1050,2SB1288,2SB1326,2SB1398..
2SB1308	Si-PNP	Strobo,30V,3A,120MHz	39b	Rhm	2SB1073,2SB1386
2SB1308-P	Si-PNP	-	39	Rhm	→2SB1308
2SB1308-Q	Si-PNP	-	39	Rhm	→2SB1308
2SB1308-R	Si-PNP	-	39	Rhm	→2SB1308

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2SB1309	Si-PNP	AF-Pow,80V,0,7A,5W,100MHz	14b	Rhm	2SB889,2SB1142,(BD140,BD170,BD238)
2SB131	Ge-PNP	AF,Sw-Pow,40V,1,5A,65W	23a$	Fui	AD149,2N2138,2N2143
2SB1310	Si-PNP-Darl	AF,Sw-Pow,40V,2A,5W,B>1000	14b	Rhm	(BD676,BD776,2SB794..795,2SB1008,+)
2SB1311	Si-PNP	AF,Sw-Pow,40V,2A,5W	14b	Rhm	2SA1359,2SB891,2SB1142
2SB1312	Si-PNP	AF,50V,2A,1,2W	7c(9mm)	Rhm	2SA1315,2SA1382,2SB892,2SB1312..
2SB1313	Si-PNP	=2SB1312:SMD	39b	Rhm	2SA1213,2SB1123..1124
2SB1314	Si-PNP	Lo-sat,Hi-beta,60V,3A,15W,100MHz	17c	Mit	-
2SB1315	Si-PNP	AF,Sw-Pow,120V,8A,65W,65MHz	18c	Mit	2SA1671..72,2SA1804..05,2SA1908..09,..
2SB1316(FS)	Si-P-Darl+Di	AF,Sw-Pow,100V,2A,10W,B=3000	30j$	Rhm	2SB908,2SB1072,2SB1303
2SB1317	Si-PNP	AF,Sw-Pow,180V,15A,150W,20MHz	77J$	Mat	2SA1302,2SA1553
2SB1318	Si-P-Darl+Di	GenP,100V,±3A,1W,B>2000	9b	NEC	2SB1484
2SB1319	Si-PNP	=2SB1288:	9c	Mat	→2SB1288
2SB131A	Ge-PNP	=2SB131:8A	23a$	-	AL100..101,2N2288,2N2291
2SB132	Ge-PNP	=2SB131:60V	23a$	Fui	AD166..167,2N2139,2N2144
2SB1320	Si-PNP	=2SB641:Pins=14mm	9c	Mat	→2SB641
2SB1320A	Si-PNP	=2SB642:Pins=14mm	9c	-	→2SB642
2SB1321	Si-PNP	=2SB643:Pins=14mm	9c	Mat	→2SB643
2SB1321A	Si-PNP	=2SB644:Pins=14mm	9c	-	→2SB644
2SB1322(A)	Si-PNP	=2SB793(A):Pins=14mm	9c	Mat	→2SB792(A)
2SB1323	Si-PNP-Digital+Di	Motor-Dr,40V,3A,R1=160Ω,R2=800Ω	39b	Sanyo	-
2SB1324	Si-PNP	-	39	Sanyo	→2SB1324
2SB1325	Si-PNP	-	39	Sanyo	→2SB1325
2SB1326	Si-PNP	=2SB1305:	9c	Rhm	→2SB1305
2SB1327	Si-PNP	HF-Pow,100V,5A,58,3W	49d	Mit	-
2SB1328	Si-PNP	GenP,160/160V,1,5A,1,2W,50MHz	78b	Rhm	2SA1225,2SA1552,2SB1275,2SB1409
2SB1329	Si-PNP	Lo-sat,40V,1A,1,2W,150MHz	78b	Rhm	2SA1241,2SB1201
2SB132A	Ge-PNP	=2SB131:60V,8A	23a$	-	AL100..101,2N2289,2N2292
2SB1330	Si-PNP	Lo-sat,80V,0,7A,1,2W,100MHz	78b	Rhm	-
2SB1331	Si-PNP	Lo-sat,40V,2A,1,2W,100MHz	78b	Rhm	2SA1241,2SB1201
2SB1332	Si-PNP	Lo-sat,80V,1A,1,2W,100MHz	78b	Rhm	2SA1593
2SB1333	Si-P-Darl+Di	=2SB1256:	78b	Rhm	2SB908,2SB1072,2SB1303
2SB1334(A)	Si-PNP	AF-Pow,80V,4A,40W,12MHz	17j$	Rhm	BD244B,BD538,BD952,2SB920L..
2SB1335(A)	Si-PNP	=2SB1334:Iso,30W	17c	Rhm	2SA1394,2SA1635,2SB1095,2SB1292..
2SB1337	Si-PNP	AF,Sw-Pow,150V,2A,40W	17j$	Rhm	BD242D,2SA940,2SB861,2SB991..
2SB1338	Si-PNP	=2SB1337:Iso,30W	17c	Rhm	2SA1332,2SB1096,2SB1530
2SB1339	Si-P-Darl+Di	AF,Sw-Pow,120V,6A,40W,12MHz,B=10000	17j$	Rhm	-
2SB134	Ge-PNP	AF,LN,30V,0,1A,0,1W	2a	Mit	AC125..126,AC151r,ACY32,2SB173
2SB1340	Si-P-Darl+Di	=2SB1339:Iso,30W	17c	-	-
2SB1341	Si-P-Darl+Di	AF,Sw-Pow,80V,4A,40W,12MHz,B=3000	17j$	Rhm	BD718,BDW24B,BDW54B,BDW64B..
2SB1342	Si-P-Darl+Di	=2SB1341:Iso,30W	17c	-	2SB1024,2SB1098,2SB1227,2SB1282,..
2SB1343	Si-P-Darl+Di	AF,Sw-Pow,100V,8A,40W,12MHz,B=10000	17j$	Rhm	BD652,BD9022,BDW47C,BDX54C..
2SB1344	Si-P-Darl+Di	=2SB1343:Iso,30W	17c	Rhm	BD650F,2SB1020,2SB1099,2SB1283..
2SB1345	Si-PNP	AF,Sw-Pow,100V,7A,80W,12MHz	16c	Rhm	(BD246C,BDV96,2SA1141,2SA1186,..)
2SB1346	Si-PNP	AF,Sw-Pow,60V,3A,30W,40MHz	17j$	Sanyo	BD242A,BD536,BD936,2SA1262..
2SB1347	Si-PNP	AF,Sw-Pow,160V,12A,120W,15MHz	77j$	Sanyo	2SA1301..02,2SB1153,2SB1162..63
2SB1348	Si-PNP	AF,160/160V,0,1A,0,4W,140MHz	7c	Hit	BF423A,BF435..437,2SA1281..
2SB1349	Si-PNP	=2SB1348:200/200V	7c	Hit	BF423A,BF435..437,2SA1370..
2SB135	Ge-PNP	AF,30V,0,1A,0,1W	2a	Mit	AC125..126,AC151,2SB54,2SB56
2SB1351	Si-P-Darl+Di	AF,Sw-Pow,60V,12A,30W,B>2000	17c	Sak	BDT64(A..C)F,(BDW45,BDW94A)
2SB1352	Si-P-Darl+Di	=2SB1351:60W	18c	Sak	BDV64F,BDV66F,(BDW84A)
2SB1353	Si-PNP	AF,Sw-Pow,120V,1,5A,1,8W,50MHz	78c	Rhm	2SB1086,2SB1144,2SB1220(A)
2SB1353A	Si-PNP	=2SB1353:160V	78c	-	2SA1249,2SB649,2SB1086A
2SB1353E	Si-PNP	120V,1.5A,1.8W,50MHz	-	-	-
2SB1354	Si-PNP	AF,Sw-Pow,60V,3A,1,8W	78c	Rhm	BD178,BD440,2N5194,2SB1217,..
2SB1355	Si-PNP	AF,Sw-Pow,80V,4A,1,8W,12MHz	78c	Rhm	BD788,BD790,MJE250..252,2N5195
2SB1356	Si-PNP	AF,Sw-Pow,80V,7A,1,8W,12MHz	78c	Rhm	-
2SB1357	Si-PNP	AF,Sw-Pow,60V,3A,1,8W,70MHz	78c	Rhm	2SB1065,2SB1217
2SB1358	Si-PNP	AF,Sw-Pow,60V,5A,1,8W,12MHz	78c	Rhm	2SB1151
2SB1359	Si-P-Darl+Di	AF,Sw-Pow,100V,2A,1,8W,B>1000	78c	Rhm	-
2SB135A	Ge-PNP	=2SB135:110V	2a	-	ACY39,2N2042..2043
2SB136	Ge-PNP	AF,25V,0,15A,0,15W	2a	Mit	AC125..126,AC151,2SB54,2SB56
2SB1360	Si-PNP	AF,Sw-Pow,100V,5A,1,8W,12MHz	78c	Rhm	-
2SB1361	Si-PNP	AF,Sw-Pow,150V,9A,100W,15MHz	16c	Mat	2SA1673,(BD246D,2SA1186,2SA1386(A)+)
2SB1362	Si-PNP	=2SB1361:	18J$	Mat	BD246D,2SA1186,2SA1386(A),2SB817..

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2SB1363	Si-PNP	AF,Sw,400/360V,0,1A,0,9W	7c(9mm)	Hit	2SA1024,2SA1372,2SA1584,2SA1760..
2SB1364	Si-PNP	AF,30V,1A	39b	Hit	BCX51..53,2SA1364,2SB766A,2SB1260,..
2SB1365	Si-PNP	AF,20V,2A	39b	Hit	2SA1363,2SA1663,2SB1121,2SB1301..
2SB1366	Si-PNP	AF,Sw-Pow,60V,3A,25W,9MHz	17c	Kec	2SA1440,2SA1488,2SA1635,2SB1335..
2SB1367	Si-PNP	AF,Sw-Pow,100V,5A,30W,5MHz	17c	Kec	BD954F,2SA1441,2SB1016,2SB1294..
2SB1368	Si-PNP	AF,Sw-Pow,80V,4A,25W,9MHz	17c	Kec	2SA1441,2SA1635,2SA1394,2SB1335..
2SB1369	Si-PNP	AF,Sw-Pow,60V,3A,40W,15MHz	17j$	Rhm	BD242,BD536,BD936,2SA1262..
2SB136A	Ge-PNP	=2SB136:60V	2a	-	ACY24,ASY48,ASY77,2SB55
2SB137	Ge-PNP	AF,Sw-Pow,30V,5A,30W	23a$	Mit	AD166..167,AL102..103,2SB231..
2SB1370	Si-PNP	=2SB1369:Iso,30W	17c	Rhm	2SA1488,2SA1635,2SB1094,2SB1335..
2SB1371	Si-PNP	AF,Sw-Pow,120V,6A,70W,15MHz	16c	Mat	2SA1671,(BD246D,2SA1146,2SA1186,..)
2SB1372	Si-PNP	AF,Sw-Pow,140V,7A,80W,15MHz	16c	Mat	2SA1672,(BD246D,2SA1146,2SA1186,..)
2SB1373	Si-PNP	AF,Sw-Pow,160V,12A,120W,15MHz	18j$	Mat	BD746F,2SA1386(A),2SA1492,2SA1516
2SB1374	Si-PNP	Lo-sat,50V,2A,1W,200MHz	7c(9mm)	Rhm	2SA1315,2SA1706,2SB892,2SB1434
2SB1375	Si-PNP	AF-Pow,60V,3A,25W,9MHz,B=100..320	17c	Tos	BD936F,2SB1015,2SB1094,2SB1274..
2SB1376	Si-PNP	GenP,50V,0,1A,1W,80MHz	9c	Mat	BC212,BC257,BC307,BC557..
2SB1377	Si-PNP	GenP,50V,0,5A,1W,200MHz	9c	Mat	BC327,BC638,BC640,2SA1705..
2SB1378	Si-PNP	GenP,25V,0,5A,0,6W,150MHz	9c	Mat	BC327..328,BC636,BC638,2SA1515..
2SB138	Ge-PNP	=2SB137:60V	23a$	Mit	AD166..167,AL102..103,2SB231..
2SB1381	Si-P-Darl+Di	AF,Sw-Pow,100V,5A,30W,B=1,5k..15k	17c	Tos	2SB1098,2SB1227..28,2SB1258,2SB1340..
2SB1382	Si-P-Darl+Di	AF,Sw-Pow,120/120V,16A,75W,B>2000	18c	Sak	BDV66CF..DF
2SB1383	Si-P-Darl+Di	AF,Sw-Pow,120/120V,25A,120W,B>2000	18j$	Sak	2SB1494
2SB1386	Si-PNP	=2SB1305:SMD	39b	Rhm	2SB1308
2SB1386-P	Si-PNP	-	39	Rhm	→2SB1386
2SB1386-Q	Si-PNP	-	39	Rhm	→2SB1386
2SB1386-R	Si-PNP	-	39	Rhm	→2SB1386
2SB1387	Si-P-Darl+Di	AF-Out,120V,1,5A,1W,120MHz,B>2000	7c(9mm)	Hit	2SB1256
2SB1388	Si-P-Darl+Di	110V,10A,45W,20MHz,B=4000	18c	Sanyo	BDV64CF,BDV66BF..DF,(BDW84D)
2SB1389	Si-P-Darl+Di	=2SB1101:Iso,25W	17c	Hit	BDT60F,2SB1223,2SB1257,2SB1342..
2SB138A,B	Ge-PNP	=2SB137:80V	23a$	Mit	AD167,AL102..103,2SB231..
2SB1390	Si-P-Darl+Di	=2SB1103:Iso,25W	17c	Hit	BD646F,BDT62F,2SB1021..22,2SB1224..
2SB1391	Si-P-Darl+Di	=2SB791:Iso,25W	17c	Hit	BD652F,BDT62CF,2SB1259
2SB1392	Si-PNP	AF-Pow,70V,4A,25W	17c	Hit	BD952F,2SA1635,2SB1017,2SB1335..
2SB1393	Si-PNP	30V,3A,2W,30MHz	-		-
2SB1393(A)	Si-PNP	=2SB929(A):25W	17c	Mat	BD936F,2SB1015,2SB1094,2SB1375..
2SB1394	Si-PNP-Digital+Di	Motor-Dr,40V,A,R1=90Ω,R2=800Ω	39b	Sanyo	-
2SB1395	Si-PNP	GenP,Lo-sat,15V,3A,0,75W	7c	Sanyo	2SB893,2SB985,2SB1117,2SB1300..
2SB1396	Si-PNP	-	39	Sanyo	→2SB1396
2SB1397	Si-PNP-Digital+Di	Lo-sat,25V,2A,R1=0,R2=1,6kΩ	39b	Sanyo	-
2SB1398	Si-PNP	=2SB1288=2SB1319:Pins=14mm	9c	Mat	→2SB1288
2SB1399	Si-P-Darl+Di	=2SB955:Iso,30W	17c	Hit	BDT62CF,2SB1259
2SB14	Ge-PNP	AF-Pre,LN,30V,0,05A,0,05W	5g	Ful	AC125..126,AC151r,ACY32,2SB173
2SB140	Ge-PNP	AF,Sw-Pow,40V,1,5A,12W	23a$	Son	AD149,2N2138,2N2143,2SB449
2SB1400	Si-P-Darl+Di	=2SB727:Iso,25W	17c	Hit	BD652F,2SB1193,2SB1340
2SB1401	Si-P-Darl+Di	AF-Pow,300V,0,3A,15W,B>1000	17c	Hit	2SB1465,(2SB1061)
2SB1402	Si-P-Darl+Di	=2SB1105:Iso,25W	17c	Hit	BDT60CF,2SB1252,2SB1340
2SB1403	Si-P-Darl+Di	=2SB1106:Iso,25W	17c	Hit	BD652F,2SB1193,2SB1340
2SB1404	Si-P-Darl+Di	=2SB765:Iso,25W	17c	Hit	BDT60CF,2SB1252,2SB1340
2SB1405	Si-PNP-Darl	80V,0,7A,1W,B>5000	9c	Sanyo	2SB865,2SB888,2SB1129
2SB1406	Si-PNP-Darl	80V,1,5A,1W,B>4000	9c	Sanyo	2SB865,2SB1129
2SB1407L,S	Si-PNP	AF-Pow,35V,2,5A,18W	30j$	Hit	2SB906,2SB962,2SB1184,2SB1202
2SB1409L,S	Si-PNP	AF-Pow,180/160V,1,5A,18W,240MHz	30j$	Hit	2SA1552
2SB141	Ge-PNP	=2SB140:60V	23a$	Son	AD166..167,2N2139,2N2144
2SB1411	Si-P-Darl+Di	Sw,Pow,100V,2A,20W,B=1,5k..15k	17c	Tos	BDT60BF,2SB1024,2SB1226,2SB1282..
2SB1412(FS)	Si-PNP	Strobo,30V,5A,120MHz	30j$	Rhm	2SA1242,2SA1795,2SB967,2SB1203,..
2SB1413	Si-PNP	AF-Pow,45V,1A,1,5W,200MHz	78b	Mat	2SB1142,(BD136,BD138,BD140,..)
2SB1414	Si-PNP	AF-Out,180/180V,1A,1,5W,200MHz	78b	Mat	(2SA1249,2SA1507,2SB649)
2SB1415	Si-P-Darl+Di	60V,1A,150MHz,B>4000	78b	Mat	-
2SB1416	Si-PNP	AF-Out/Sw,60V,3A,1,5W,500/1500nS	78b	Mat	2SB1143,(BD178,BD180,BD190)
2SB1417	Si-PNP	AF-Out/Sw,60V,3A,15W,30MHz	78c	Mat	BD936F,2SA1488,2SB1274,2SB1375..
2SB1417A	Si-PNP	=2SB1417:80V	78c	-	2SA1488A,2SB1017,2SB1335
2SB1418	Si-P-Darl+Di	AF-Out/Sw,60V,2A,15W,20MHz,B>1000	78c	Mat	BDT60F,2SB1223,2SB1342,2SB1411
2SB1418A	Si-P-Darl+Di	=2SB1418:80V	78c	-	BDT60AF,2SB1282,2SB1342,2SB1411
2SB1419	Si-PNP	AF-Pow,160/160V,12A,120W	77j$	Mat	2SA1301..1302,2SB1162,2SB1347

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2SB142	Ge-PNP	AF,Sw-Pow,30V,1A,10W,B>12	23a$	Son	AD149,2N2137,2N2142,2SB449
2SB1420	Si-P-Darl+Di	Sw,Pow,120V,16A,80W,50MHz,B>2000	18j$	Sak	BDV66B..D,BDW84D
2SB1421	Si-PNP	AF-Pow,140/140V,7A,80W,15MHz	18j$	Mat	2SA1146,2SA1186,2SA1265,2SA1491..
2SB1422	Si-P-Darl+Di	AF-Pow,Int.Z-Diode,60V,1A,5W,B>4000	14h$	Mat	(BD680,2SB1034)
2SB1423	Si-PNP	=2SB1412:	14h$	Rhm	2SA1120
2SB1424	Si-PNP	=2SB1426:SMD	39b	Rhm	2SA1730,2SB1518
2SB1424-P	Si-PNP	-	39	Rhm	→2SB1424
2SB1424-Q	Si-PNP	-	39	Rhm	→2SB1424
2SB1424-R	Si-PNP	-	39	Rhm	→2SB1424
2SB1425	Si-PNP	Lo-sat,20V,2A,1W,90MHz	7c(9mm)	Rhm	2SA1315,2SB733,2SB892,2SB1434,..
2SB1426	Si-PNP	AF,Lo-sat,20V,3A,0,75W,240MHz	7c	Rhm	2SB1117,2SB1505
2SB1427	Si-PNP	Hi-beta,-/20V,2/3A,B=270..1200	39b	Rhm	2SA1369
2SB1427-E	Si-PNP	-	39	Rhm	→2SB1427
2SB1427-S	Si-PNP	-	39	Rhm	→2SB1427
2SB1427-U	Si-PNP	-	39	Rhm	→2SB1427
2SB1428	Si-PNP	=2SB1426:0,6W	9c	Rhm	2SB1117,2SB1505
2SB1429	Si-PNP	AF-Pow,180V,15A,150W,10MHz	77j$	Tos	2SA1302,2SA1553
2SB143(P)	Ge-PNP	=2SB142:B>23	23a$	Son	AD149,2N2137,2N2142,2SB449
2SB1430	Si-P-Darl+Di	AF,Sw-Pow,100/100V,5A,20W,B>2000	17c	Nec	2SB1089,2SB1227,2SB1258,2SB1340
2SB1431	Si-P-Darl+Di	AF,Sw-Pow,100/100V,8A,25W,B>2000	17c	Nec	2SB1099,2SB1228,2SB1283,2SB1344
2SB1432	Si-P-Darl+Di	AF,Sw-Pow,100/100V,10A,30W,B>1000	17c	Nec	BDT62BF..CF,2SB110,2SB1259,2SB1284
2SB1433	Si-PNP	AF-Pow,Lo-sat,50V,2A,0,9W	7c(9mm)	Hit	2SA1315,2SB892,2SB985
2SB1434	Si-PNP	AF-Pow,Lo-sat,50V,2A,1W,110MHz	9c	Mat	2SA1706,2SB892,2SB1229
2SB1435	Si-PNP	=2SB1434:1,5W,80MHz	78b	Mat	(2SB986,2SB1142)
2SB1436	Si-PNP	=2SB1412:	14b	Rhm	2SA1357
2SB1437	Si-PNP	AF-Pow,Lo-sat,100V,1A,1W,120MHz	9c	Mat	2SA1708,(BC640,2SB647,2SB984)
2SB1438	Si-PNP	AF-Pow,Lo-sat,100V,2A,1W,90MHz	9c	Mat	2SA1709
2SB1439	Si-PNP	=2SB1438:1,5W,200MHz	78b	Mat	-
2SB144(P)	Ge-PNP	=2SB142:B>45	23a$	Son	AD149,2N2137,2N2142,2SB449
2SB1440	Si-PNP	-	39	Mat	→2SB1440
2SB1440-R	Si-PNP	-	39	Mat	→2SB1440
2SB1440-S	Si-PNP	-	39	Mat	→2SB1440
2SB1443	Si-PNP	=2SB1374:	9c	Rhm	→2SB1374
2SB1446	Si-PNP	GenP,50V,5A,1W,70MHz	9c	Mat	2SB1483
2SB1447	Si-PNP	AF,Lo-sat,50V,3A,1,5W,250MHz	78b	Mat	2SB1143,(2SB986,2SB1217)
2SB1448	Si-PNP-Darl	=2SB1285:Iso,65W	18c	Shi	BDV66AF,(BDW84C,2SB1285)
2SB1449	Si-PNP	Sw,Pow,Lo-sat,60V,5A,30W,100/900nS	30j$	Sanyo	2SB1268,2SB1270,2SB1451
2SB145	Ge-PNP	=2SB142:gep,B=37	23a$	Son	AD149,2N2137,2N2142,2SB449
2SB1450	Si-PNP	Sw,Pow,Lo-sat,60V,7A,40W,200/800nS	30j$	Sanyo	2SB1269,2SB1271,2SB1452
2SB1451	Si-PNP	Sw,Pow,Lo-sat,90V,5A,30W,200/900nS	30j$	Sanyo	2SB1270..71,2SB1452
2SB1452	Si-PNP	Sw,Pow,Lo-sat,90V,7A,40W,200/900nS	30j$	Sanyo	2SB1271
2SB1453	Si-PNP	Sw,Pow,60V,3A,5MHz,400/2200nS	17c	Nec	BD936F,2SB1015,2SB1094,2SB1375,..
2SB1454	Si-PNP	Sw,Pow,Lo-sat,90V,5A,25W,20MHz	17c	Sanyo	2SA1388,2SA1441,2SA1741,2SB1018..
2SB1455	Si-PNP	Sw,Pow,Lo-sat,90V,7A,30W,20MHz	17c	Sanyo	2SA1442,2SA1742,2SB1018
2SB1456	Si-PNP	AF,Lo-sat,150V,1A,1W,120MHz	9c	Mat	-
2SB1457	Si-P-Darl+Di	AF,Sw,100V,2A,0,9W,B>2000	7c(9mm)	Tos	2SB1256,2SB1387,2SB1318
2SB1459	Si-PNP	=2SB1433:80V	7c(9mm)	Hit	2SA1315,2SB1438
2SB146	Ge-PNP	=2SB142:gep,B=75	23a$	Son	AD149,2N2137,2N2142,2SB449
2SB1460	Si-PNP	=2SB1425:	9c	Rhm	→2SB1425
2SB1461	Si-PNP	Hi-beta,-/20V,2/3A,B=270..1200	78b	Rhm	-
2SB1462	Si-PNP	-	35(1,6mm)	Mat	→2SB1462
2SB1462(J)	Si-PNP	GenP,60V,0,1A,80MHz	35a(1,6mm)	Mat	2SA1832
2SB1462J	Si-PNP	-	35(1,6mm)	Mat	→2SB1462
2SB1462-Q	Si-PNP	-	35(1,6mm)	Mat	→2SB1462
2SB1462-R	Si-PNP	-	35(1,6mm)	Mat	→2SB1462
2SB1462-S	Si-PNP	-	35(1,6mm)	Mat	→2SB1462
2SB1463	Si-PNP	GenP,150V,0,05A,200MHz	35a(1,6mm)	Matsushita	-
2SB1463-R	Si-PNP	-	35(1,6mm)	Mat	→2SB1463
2SB1463-S	Si-PNP	-	35(1,6mm)	Mat	→2SB1463
2SB1463-T	Si-PNP	-	35(1,6mm)	Mat	→2SB1463
2SB1464	Si-P-Darl+Di	Sw,Pow,60V,8A,25W,20MHz,B>2000	17c	Mat	2SB1021..22,2SB1224..25
2SB1465	Si-PNP-Darl	Sw,Pow,300/300V,0,3A,25W,25MHz,B>1500	17c	Nec	2SB1401
2SB1466	Si-P-Darl+Di	Sw,Pow,100/100V,15A,100W,B>1000	18j$	Hit	BDV66A..D,BDW84C..D,2SB969
2SB1467	Si-PNP	Sw,Pow,60V,8A,20W,120MHz,100/230nS	17c	Sanyo	2SA1442,2SA1470,2SA1742

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2SB1468	Si-PNP	Sw,Pow,60V,12A,25W,120MHz,100/330nS	17c	Sanyo	2SA1451..52,2SA1568,2SA1771
2SB1469	Si-PNP-Darl	Pow,160/140V,7A,100W,20MHz,B>5000	18j$	Mat	2SB1493
2SB147	Ge-PNP	AF,Sw-Pow,60V,1,5A,12W	23a$	Son	AD166..167,2N2139,2N2144
2SB1470	Si-PNP-Darl	Pow,160/160V,8A,150W,20MHz,B>5000	77j$	Mat	2SB1490,2SD1503
2SB1471	Si-PNP-Darl	Pow,70V,4A,30W,500/2600nS,B>2000	30j$	Sanyo	(BDW24B..C,BDW64B..D,2SB1342,..)
2SB1472	Si-PNP-Darl	Pow,70V,7A,35W,500/2900nS,B>2000	30j$	Sanyo	(BD648,BD900,BDW74B..D,2SB1020,..)
2SB1473	Si-PNP	=2SB987:Pins=14mm	9c	Mat	→2SB987
2SB1474(FS)	Si-P-Darl+Di	Pow,80V,4A,10W,12MHz,B>1000	30j$	Rhm	2SB908,2SB1072
2SB1475	Si-PNP	GenP,25V,0,5A,>50MHz	35a(2mm)	NEC	BC807W..808W,2SB1219(A)
2SB1475-B42	Si-PNP	-	35(2mm)	Nec	→2SB1475
2SB1475-B43	Si-PNP	-	35(2mm)	Nec	→2SB1475
2SB1475-B44	Si-PNP	-	35(2mm)	Nec	→2SB1475
2SB1476	Si-P-Darl+Di	AF-Pow,120/120V,6A,60W,B>2000	18j$	Sak	2SA1183,2SB1557
2SB1477	Si-PNP	Pow,-/100V,5A,60W	16c	Rhm	2SA1671,(BD246D,2SA1146,2SA1186,..)
2SB1478	Si-P-Darl+Di	Pow,-/100V,8A,60W,B>2000	16c	Rhm	BDV64C,BDV66B,BDW84D
2SB148	Ge-PNP	Sw,Pow,80V,15A,40W	-	Tos	(2N1551..52,2N1555..56,2N1559..60,..)
2SB1481	Si-P-Darl+Di	Sw,Pow,100V,±4A,25W,150/1200nS,B>2k	17c	Tos	BDT60BF,2SB1020,2SB1024,2SB1282..
2SB1482	Si-PNP	Strobo,-/20V,5A,1,2W	78b	Rhm	2SA1242,2SB1288,2SB1306,2SB1446..
2SB1483	Si-PNP	Lo-sat,60/60V,5A,1W	9b	NEC	-
2SB1484	Si-P-Darl+Di	GenP,100/100V,±3A,1W,B=2k..20k	9b	Nec	2SB1318
2SB1485M	Si-PNP	=2SB1374:	9c	Rhm	→2SB1374
2SB1488	Si-PNP	Sw,400/400V,0,5A,1W,25MHz	9c	Mat	2SA1625,2SB1074
2SB1489	Si-PNP	Sw,400/400V,0,6A,1,5W,100MHz	78b	Mat	(2SA1156,2SA1498)
2SB149	Ge-PNP	AF,Sw-Pow,40V,8A,25W	-	Tos	AL100..101,2N2288,2N2291..
2SB1490	Si-PNP-Darl	Sw,Pow,160/140V,7A,90W,20MHz,B>5000	77j$	Mat	2SB1470,2SB1503
2SB1492	Si-PNP-Darl	Pow,130/110V,6A,70W,20MHz,B>5000	77j$	Mat	2SB1470,2SB1490,2SB1503
2SB1493	Si-PNP-Darl	Pow,160/140V,7A,70W,20MHz,B>5000	18j$	Mat	2SB1469,2SB1560
2SB1494	Si-P-Darl+Di	Sw,Pow,120/120V,25A,120W,B>2000	18j$	Hit	2SB1383
2SB1495	Si-P-Darl+Di	Sw,Pow,100V,3A,20W,500/1400nS,B>2k	17c	Tos	BDT60BF,2SB1226,2SB1250,2SB1282,..
2SB1496	Si-PNP	GenP,60V,3A,1,8W,15MHz	78c	Rhm	(BD178,BD190,2SB1184,2SB1202,..)
2SB1497	Si-PNP	GenP,60V,3A,1W,50MHz,150/600nS	9b	NEC	2SA1066,2SA1707,2SA1761
2SB1498	Si-PNP	Sw,Pow,600/600V,0,3A,15W,<1/4µS	?30j$	Mat	-
2SB1499	Si-PNP	AF,Sw-Pow,60V,4A,15W,30MHz,200/700nS	78c	Mat	(2SA1388,2SA1469..70,2SA1441)
2SB1499A	Si-PNP	=2SA1499:80V	78c	-	(2SA1388,2SA1469..70,2SA1441)
2SB149N	Ge-PNP	=2SA149:60V,7A	-		AL100..103,2N2289,2N2292..
2SB15	Ge-PNP	AF-Pre,60V,0,05A,0,05W	5g	Fui	ACY24,ASY48,2SB55
2SB150	Ge-PNP	Sw,105V,0,04A,0,05W	2a	Tos	ACY39,2N2042..2043
2SB1500	Si-PNP-Darl	Pow,100/80V,3A,45W,20MHz,B>5000	77j$	Mat	2SB1492
2SB1501	Si-PNP-Darl	Pow,110/90V,4A,50W,20MHz,B>5000	77j$	Mat	2SB1492
2SB1502	Si-PNP-Darl	Pow,120/100V,5A,60W,20MHz,B>5000	77j$	Mat	2SB1492,2SB1555..56
2SB1503	Si-PNP-Darl	Pow,160/140V,8A,120W,20MHz,B>5000	77j$	Mat	2SB1470,2SB1490
2SB1504	Si-P-Darl+Di	Sw,Pow,50V,8A,20MHz,500/3000nS,B>1000	78b	Mat	(BD646,BD898,BDW74A..D,2SB1464,..)
2SB1505	Si-PNP	Lo-sat,30V,3A,0,9W	7c(9mm)	Hit	2SB985,2SB1117,2SB1592
2SB1507	Si-PNP	Sw,Pow,60V,7A,40W,10MHz,200/800nS	18c	Sanyo	2SA1670,2SB1371,(BD246A..F,..)
2SB1508	Si-PNP	Sw,Pow,60V,12A,45W,10MHz,100/500nS	18c	Sanyo	(BD546A..D,2SA1292,2SB828..829,..)
2SB1509	Si-PNP	Sw,Pow,60V,15A,50W,20MHz,200/600nS	18c	Sanyo	(BD546A..D,2SA1292,2SB828..829,..)
2SB151	Ge-PNP	AF,Sw-Pow,80V,5A,50W	23a$	Fui	AL102..103,2N3615,2N3617,2SB231..
2SB1510	Si-P-Darl+Di	Dr,80V,3A,B>2000,1,5W	?12b	Sanyo	(BUT60AF,2SB1282,2SB1342,2SB1568,..)
2SB1511	Si-PNP	Sw,Pow,60V,20A,40W,120MHz,300/320nS	18c	Sanyo	(2SB904)
2SB1512	Si-P-Darl+Di	Pow,-/80V,4A,1,8W,B>1000	78c	Rhm	2SB908,2SB1072
2SB1513	Si-P-Darl+Di	Pow,-/120V,6A,1,8W,B>2000	78c	Rhm	-
2SB1514	Si-P-Darl+Di	Pow,-/100V,8A,1,8W,B>1000	78c	Rhm	-
2SB1515	Si-P-Darl+Di	AF,80V,4A,1,2W,12MHz,B=5000	78b	Rhm	2SB908,2SB1072
2SB1516(FS)	Si-PNP	AF-Pow,80V,3A,10W,18MHz	30j$	Rhm	2SB1215..16,(BD190,BD442,..)
2SB1517	Si-PNP	AF-Driver,-/50V,3A,1,2W	78b	Rhm	2SA1761,2SB906,2SB965,2SB1184..
2SB1518	Si-PNP	=2SB1505:SMD	39b	Hit	2SA1736,2SB1124
2SB1518-D	Si-PNP	-	39	Hit	→2SB1518
2SB1518-E	Si-PNP	-	39	Hit	→2SB1518
2SB1519	Si-PNP	-	39	Hit	→2SB1519
2SB152(A)	Ge-PNP	=2SB151:100V	23a$	Fui	AL102..103,2N3616,2N3618,2SB231..
2SB1520	Si-PNP	-	39	Hit	→2SB1520
2SB1522K	Si-PNP	GenP,15V,1A,200MHz	35	Rhm	-
2SB1526	Si-P-Darl+Di	Sw,Pow,60V,2A,20MHz,0,4/2µS,B>1000	78b	Mat	(BD778,BD780,2SB794..95,2SB1067,..)
2SB1527	Si-PNP+Diode	R2=1kΩ,20V,0,8A,250MHz	35a	Sanyo	-

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2SB1528	Si-PNP	AF-Pow,-/160V,12A,120W	77j$	Mat	2SA1301,2SB1162,2SB1347
2SB1529	Si-PNP	AF-Pow,180/180V,15A,150W,45MHz	77j$	Mat	2SA1302,2SB1163,2SB1317,2SB1429
2SB153	Ge-PNP	AF,12V,0,07A,0,15W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB1530	Si-PNP	AF-Pow,200/150V,2A,20W	17c	Hit	2SA1306B,2SA1668,2SB1096
2SB1531	Si-PNP-Darl	AF,Sw-Pow,130/110V,6A,50W,20MHz	18j$	Mat	2SB1469,2SB1493,2SB1557..58
2SB1532	Si-PNP	AF-Pow,40V,10A,40W	17c	Fjd	2SA1327,2SA1567,2SA1599,2SB948(A)
2SB1535(FS)	Si-PNP	AF-Pow,100/100V,6A,10W,18MHz	30j$	Rhm	(BD244C..F,BD540C..D,BD954,2SB633)
2SB1536	Si-PNP	GenP,30V,5A,1,2W,120MHz	?12b	Mat	(2SA1307,2SA1469,2SA1643)
2SB1537	Si-PNP	Lo-sat,10V,1A,120MHz	39b	Mat	2SA1314,2SA1734,2SB1121
2SB1538	Si-PNP	=2SB1537:	9d	Mat	BC636,2SA1705,2SB909,2SB1116..
2SB1539	Si-PNP	Lo-sat,20V,1A,120MHz	39b	Mat	2SA1314,2SA1734,2SB1121
2SB154	Ge-PNP	AF,12V,0,07A,0,15W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB1540	Si-PNP	GenP,-/20V,0,5A	9	Mat	BC327,2SA1426,2SA1705,2SB1116..
2SB1541	Si-PNP	GenP,60V,1A,1,2W,150MHz	?12b	Mat	(BD518,BD526,2SA962,2SB1201,..)
2SB1542	Si-PNP	GenP,50V,2A,1,2W,140MHz	?12b	Mat	(BD510,BD516,2SA1241,2SB1201,..)
2SB1543	Si-PNP	GenP,60V,3A,1,2W,30MHz	?12b	Mat	(2SA1876,2SB906,2SB1184,2SB1202,..)
2SB1544	Si-PNP	GenP,80V,1A,1,2W,130MHz	?12b	Mat	(BD520,BD528,BD530,2SA1593,..)
2SB1545	Si-PNP	GenP,150V,1A,1,2W,110MHz	?12b	Mat	(2SA1014,2SA1225,2SB905,2SB1275,..)
2SB1546	Si-PNP	Sw,400/400V,0,5A,1,2W,25MHz	?12b	Mat	(2SA1156,2SA1498,2SA17272SA1772)
2SB1548(A)	Si-PNP	AF,Sw-Pow,80V,3A,25W,30MHz	17c	Mat	BDT32AF..CF,2SA1338,2SA1441,2SB1565+
2SB1549	Si-P-Darl+Di	AF,80V,10A,1,8W,12MHz,B=7000	78c	Rhm	-
2SB155	Ge-PNP	AF-Dr/Out,16V,0,3A,0,15W	2a	Hit	AC128,AC153,AC188,2SB405,2SB475
2SB1550	Si-P-Darl+Di	=2SB1549:40W	17j$	Rhm	-
2SB1551	Si-P-Darl+Di	=2SB1549:30W	17c	Rhm	-
2SB1553	Si-PNP	AF,Sw-Pow,Hi-beta,80V,3A,15W,30MHz	78c	Mat	(2SB1299,2SB1314)
2SB1554	Si-PNP	AF,Sw-Pow,Hi-Ueb,60V,4A,15W,25MHz	78c	Mat	-
2SB1555	Si-PNP-Darl	AF,Sw-Pow,140/140V,7A,100W,B>5000	77j$	Tos	2SB1470,2SB1490,2SB1503
2SB1556	Si-PNP-Darl	AF,Sw-Pow,140/140V,8A,120W,B>5000	77j$	Tos	2SB1470,2SB1490,2SB1503
2SB1557	Si-PNP-Darl	=2SB1555:70W	18j$	Tos	2SB1469,2SB1493
2SB1558	Si-PNP-Darl	=2SB1556:80W	18j$	Tos	2SB1560
2SB1559	Si-PNP-Darl	AF-Pow,160/150V,8A,80W,65MHz,B>5000	18j$	Sak	(BDV66D)
2SB156(H)	Ge-PNP	AF-Dr/Out,16V,0,3A,0,15W	2a	Hit	AC128,AC153,AC188,2SB405,2SB475
2SB1560	Si-PNP-Darl	AF-Pow,160/150V,10A,100W,50MHz,B>5000	18j$	Sak	(BDV66D)
2SB1561	Si-PNP	Lo-sat,60V,2A,150MHz	39b	Rhm	2SA16891SB1123
2SB1561-P	Si-PNP	-	39	Rhm	→2SB1561
2SB1561-Q	Si-PNP	-	39	Rhm	→2SB1561
2SB1562	Si-PNP	Hi-beta,60V,3A,25W,B=300..1000	17c	Tos	2SB1299,2SB1314
2SB1565	Si-PNP	AF-Pow,80V,3A,25W,15MHz	17c	Rhm	BD938F,BDT32..F,2SA1488A,2SA1635,..
2SB1566	Si-PNP	AF-Pow,60V,3A,25W,60MHz	17c	Rhm	BD936F,BDT32..F,2SB1187,2SB1375,..
2SB1567	Si-P-Darl+Di	AF-Pow,100V,2A,20W,B=1k..10k	17c	Rhm	2SB1226,2SB1250,2SB1411,2SB1495,..
2SB1568	Si-P-Darl+Di	AF-Pow,80V,4A,30W,12MHz,B=1k..10k	17c	Rhm	BDT60..F,2SB1024,2SB1282,2SB1342,..
2SB1569	Si-PNP	AF-Pow,120V,1,5A,20W,50MHz	17c	Rhm	2SA1332,2SA1393,2SB1186(A),2SA1859(A)
2SB1569A	Si-PNP	=2SB1569:160V	17c	Rhm	2SA1832,2SB1186A,2SA1606,2SA1859A
2SB156A(AH)	Ge-PNP	=2SB156:20V	2a	-	AC128,AC153,AC188,2SB405,2SB475
2SB157	Ge-PNP	Min,AF,7V,5mA,0,01W,B=35	37a	Mat	OC57
2SB1570	Si-PNP-Darl	AF-Pow,160/150V,12A,150W,50MHz.B>5000	20j$	Sak	-
2SB1571	Si-PNP	Lo-sat,50V,5A,150MHz,265/400nS	39b	Nec	2SB1578
2SB1571-FX	Si-PNP	-	39	Nec	→2SB1571
2SB1571-FY	Si-PNP	-	39	Nec	→2SB1571
2SB1571-FZ	Si-PNP	-	39	Nec	→2SB1571
2SB1572	Si-PNP	Lo-sat,80V,3A,160MHz,155/545nS	39b	Nec	-
2SB1572-HX	Si-PNP	-	39	Nec	→2SB1572
2SB1572-HY	Si-PNP	-	39	Nec	→2SB1572
2SB1572-HZ	Si-PNP	-	39	Nec	→2SB1572
2SB1573	Si-PNP	AF,Sw-Pow,60V,3A,10W,270MHz	30j$	Mat	2SB906,2SB1184,2SB1202,2SA1876
2SB1574	Si-PNP	AF,Sw-Pow,50V,2A,10W,150MHz	30j$	Mat	2SB838,2SB1184,2SB1201,2SB1241
2SB1575	Si-PNP	AF,Sw-Pow,50V,5A,10W,70MHz	30j$	Mat	2SA1732,2SB1204,2SA1796,2SA1877
2SB1576	Si-PNP-Darl	Pow,-/100V,2A,B=1..10k	30j$	Mat	2SB1303,2SB1316
2SB1578	Si-PNP	Sw,60V,5A,600/600nS	39b	Nec	(2SB1571)
2SB1578-GB1	Si-PNP	-	39	Nec	→2SA1578
2SB1578-GB2	Si-PNP	-	39	Nec	→2SA1578
2SB1578-GB3	Si-PNP	-	39	Nec	→2SA1578
2SB158	Ge-PNP	=2SB157:a=55	37a	Mat	OC58
2SB1580	Si-P-Darl+Di	GenP,100/100V,2A,B=1k..10k	39b	Rhm	-

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2SB1581	Si-PNP	Lo-sat, 16V, 3A	39b	Nec	2SA1736, 2SB1124, 2SB1518
2SB1582	Si-PNP	GenP, 30V, 0,5A, 200MHz	35d	Mat	BC807R..808R, BCX17R..18R, 2SA1326,..
2SB1582-Q	Si-PNP	-	?35	Mat	→2SB1582
2SB1582-R	Si-PNP	-	?35	Mat	→2SB1582
2SB1582-S	Si-PNP	-	?35	Mat	→2SB1582
2SB1583	Si-PNP	GenP, 185V, 0,05A, 200MHz	35d	Mat	-
2SB1583-Q	Si-PNP	-	?35	Mat	→2SB1583
2SB1583-R	Si-PNP	-	?35	Mat	→2SB1583
2SB1583-S	Si-PNP	-	?35	Mat	→2SB1583
2SB1584	Si-PNP	Lo-sat, 25V, 0,5A, 150MHz	35d	Mat	2SA1298
2SB1584-Q	Si-PNP	-	?35	Mat	→2SB1584
2SB1584-R	Si-PNP	-	?35	Mat	→2SB1584
2SB1584-S	Si-PNP	-	?35	Mat	→2SB1584
2SB1585	Si-PNP	Lo-sat, 15V, 0,5A, 130MHz	35d	Mat	2SA1298
2SB1585-Q	Si-PNP	-	?35	Mat	→2SB1585
2SB1585-R	Si-PNP	-	?35	Mat	→2SB1585
2SB1585-S	Si-PNP	-	?35	Mat	→2SB1585
2SB1586	Si-P-Darl+Di	AF-Pow, 120/120V, 6A, 60W, 80MHz, B>2000	18c	Sak	2SB1253..1255, (2SB1469, 2SB1493)
2SB1587	Si-P-Darl+Di	AF-Pow, 160/150V, 8A, 70W, 65MHz, B>5000	18c	Sak	2SB1254..1255, (2SB1469, 2SB1493)
2SB1588	Si-P-Darl+Di	AF-Pow, 160/150V, 10A, 70W, 50MHz, B>5000	18c	Sak	2SB1255, (2SB1560)
2SB1589	Si-PNP	Lo-sat, 10V, 1A, 190MHz	39b	Mat	BC869, BCX69, 2SA1734
2SB159	Ge-PNP	=2SB157: a=80	37a	Mat	OC59
2SB1590K	Si-PNP	Lo-sat, 15V, 1A, 200MHz	35a	Rohm	2SB1051K
2SB1592	Si-PNP	GenP, Lo-sat, 30V, 3A, 150MHz	7c(9mm)	Mat	2SA1707, 2SB985, 2SB1117, 2SB1505
2SB1593	Si-PNP	AF-Pow, Lo-sat, 29V, 3A, 200MHz	78b	Mat	2SA1359, 2SB1143
2SB1594	Si-PNP-Darl	Pow, 160/160V, 10A, 150W, 30MHz, B>3000	77j$	Tos	-
2SB1595	Si-PNP	AF-Dr/Out, -/32V, 2A, 0,9W	7c(9mm)	Rhm	2SA1315, 2SB892, 2SB1459
2SB1596	Si-PNP	AF-Driver, -/160V, 1,5A, 0,9W	7c(9mm)	Rhm	2SA1770, 2SB1130A, 2SB1212, 2SB1236A
2SB1597	Si-PNP	GenP, 50/25V, 1A	40	Mat	BC638, BC640, 2SB647, 2SB1116(A)..
2SB1598	Si-PNP	GenP, -/40V, 1,5A	40	Mat	2SB819, 2SB892, 2SB1130, 2SB1236..
2SB1599	Si-PNP	GenP, 50V, 1,5A, 150MHz	39b	Mat	2SA1213, 2SB1123, 2SB1313, 2SB1519..
2SB16	Ge-PNP	AF, 16V, 0,6A, 1,8W	?2b	Fui	(AD162, 2SB493)
2SB160	Ge-PNP	=2SB157: AF-Pow, B=75	37a	Mat	OC60
2SB1600	Si-PNP	GenP, -/100V, 1A	39b	Mat	2SA1416..17, 2SB1025..26
2SB1601	Si-PNP	GenP, -/150V, 1A	39b	Mat	2SB1027..28, 2SB1419
2SB1602	Si-PNP	Hi-beta, 60V, 3A, 1,3W, B>800	12b	Tos	-
2SB1603	Si-PNP	AF, Sw-Pow, Lo-sat, 40V, 4A, 25W, 150MHz	17c	Mat	2SA1388, 2SA1469..70, 2SA1441
2SB1603A	Si-PNP	=2SB1603: 50V	17c	-	2SA1388, 2SA1469..70, 2SA1441
2SB1604	Si-PNP	AF, Sw-Pow, Lo-sat, 40V, 10A, 40W, 100MHz	17c	Mat	2SA1327, 2SA1567, 2SB948(A)
2SB1604A	Si-PNP	=2SB1604: 50V	17c	-	2SA1327, 2SA1567, 2SB948A
2SB1605	Si-PNP	AF, Sw-Pow, 50V, 3A, 35W, 30MHz, 500/1500nS	17c	Mat	2SB1185, 2SB1274, 2SB1314
2SB1605A	Si-PNP	=2SA1605: 80V	17c	-	2SA1440
2SB1606	Si-PNP	AF, Sw-Pow, Lo-sat, 130V, 5A, 40W, 30MHz	17c	Mat	2SA1650, 2SB945
2SB1607	Si-PNP	AF, Sw-Pow, Lo-sat, 130V, 7A, 40W, 30MHz	17c	Mat	2SA1651, 2SB946
2SB161	Ge-PNP	AF-Pow, 30V, 0,1A, 0,125W, B=50	2a	Nec	AC125..126, AC151..152, 2SB475
2SB1610	Si-PNP	Lo-sat, 10V, 0,5A, 120MHz	35d	Mat	2SA1298, 2SA1753, 2SB1584..85
2SB1611	Si-PNP	Lo-sat, 20V, 0,5A, 100MHz	35d	Mat	2SA1298, 2SA1753, 2SB1584
2SB1612	Si-PNP	Lo-sat, 10V, 2A, 60MHz	39b	Mat	2SA1363, 2SA1314, 2SB1121
2SB1613	Si-PNP	GenP, -/10V, 2A	9	Mat	2SB738..739, 2SB926..927, 2SB1460..
2SB1614	Si-PNP	Lo-sat, 20V, 2A, 60MHz	39b	Mat	2SA1363, 2SA1314, 2SB1121
2SB1616	Si-P-Darl+Di	Pow, 80/80V, 4A, 30W, 20MHz, B>1000	17c	Rhm	2SB1098, 2SB1227, 2SB1282
2SB1617	Si-P-Darl+Di	100V, 2A, 1,3W, 50MHz, B>2000	12b	Tos	(2SB1316)
2SB1618	Si-PNP	-	35(2mm)	Mat	→2SB1618
2SB1619	Si-PNP	-	35(2mm)	Mat	→2SB1619
2SB162	Ge-PNP	=2SB161: 0,18W	2ao	Nec	AC125..126, AC151..152, 2SB475
2SB1620	Si-PNP-Darl	Pow, 200/200V, 12A, 130W, 60MHz, B>5000	18j	Sak	-
2SB1621	Si-PNP-Darl	=2SB1620: 17A, 200W	20j	Sak	-
2SB1622	Si-PNP-Darl	=2SB1620: Iso, 85W	18c	Sak	-
2SB1623	Si-PNP-Darl	Pow, 60V, 4A, 40W, 20MHz, B>1000	17c	Mat	BDT60F..CF, 2SB1024, 2SB1282, 2SB1381..
2SB1624	Si-PNP-Darl	AF-Pow, 110/110V, 6A, 60W, 60MHz, B>5000	18j$	Sak	2SB1469, 2SB1493, 2SB1557
2SB1625	Si-PNP-Darl	=2SB1624: Iso	18c	Sak	2SB1253..54, 2SD1587
2SB1626	Si-PNP-Darl	=2SB1624: Iso, 30W	17c	Sak	2SB1340
2SB1627	Si-PNP	Lo-sat, 45V, 0,1A, 80MHz	35d	Mat	BC856, BC860, BCW69..70
2SB1627-Q	Si-PNP	-	?35	Mat	→2SB1627

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2SB1627-R	Si-PNP	-	?3S	Mat	→2SB1627
2SB1627-S	Si-PNP	-	?3S	Mat	→2SB1627
2SB1628	Si-PNP	Lo-sat, 20V, 3A, 320MHz, 70/150nS	39b	Nec	2SB1301, 2SC1518
2SB1628-ZX	Si-PNP	-	39	Nec	→2SB1628
2SB1628-ZY	Si-PNP	-	39	Nec	→2SB1628
2SB1628-ZZ	Si-PNP	-	39	Nec	→2SB1628
2SB1629	Si-PNP	Hi-beta, 60V, 3A, 40W, B=300..700	17c	Mat	2SB1299, 2SB1314, 2SB1562
2SB163	Ge-PNP	=2SB161: B=75	2a	Nec	AC125..126, AC151..152, 2SB475
2SB1630	Si-PNP	=2SB1629:	78	Mat	-
2SB1631	Si-PNP	=2SB1629: 15W	78c	Mat	(2SB1299, 2SB1314, 2SB1562)
2SB1632	Si-PNP	Sw, 400/400V, 0,5A, tf=1µS	30j$	Mat	2SA1400, 2SA1727, 2SA1772
2SB1638	Si-PNP	Sw, Pow, Lo-sat, 40V, 7A, 15W, 150MHz	?30j$	Mat	-
2SB1638A	Si-PNP	=2SB1638: 50V	?30j$	-	-
2SB1639	Si-PNP	Hi-beta, 60V, 3A, 20W, 60MHz, B>400	17c	Rhm	2SB1299, 2SB1314, 2SB1562
2SB164	Ge-PNP	=2SB163: 0,18W	2ao	Nec	AC125..126, AC151..152, 2SB475
2SB1640	Si-PNP	AF, 60V, 3A, 1,8W, 9MHz	15c	Tos	(BD786, 2SB986, 2SB1065, 2SB1217)
2SB1641	Si-P-Darl+Di	100V, 5A, 1,8W, B=1,5k..15k	15c	Tos	-
2SB1642	Si-PNP	AF-Pow, 60V, 4A, 25W, 9MHz	17c	Tos	2SA1307, 2SA1469, 2SB1134..1135
2SB1643	Si-PNP	Hi-beta, 60V, 3A, 40W, B=300..700	30j$	Mat	-
2SB1644	Si-PNP	AF, Sw-Pow, 80V, 4A, 30W, 12MHz	30j$	Rhm	2SB1270, 2SB1451
2SB1645	Si-PNP-Darl	Pow, 160/160V, 8A, 120W, 20MHz, B>3500	77j$	Mat	2SB1470, 2SB1490, 2SB1503, 2SB1594
2SB1647	Si-PNP-Darl	AF-Pow, 150V, 15A, 130W, B>5000, 45MHz	18j$	Sak	-
2SB1648	Si-PNP-Darl	=2SB1647: 17A	20j$	Sak	-
2SB1649	Si-PNP-Darl	=2SB1647: Iso	18c	Sak	-
2SB165	Ge-PNP	=2SB161: B=100	2a	Nec	AC125..126, AC151..152, 2SB475
2SB1651	Si-PNP	GenP, 55V, 0,05A, 0,4W, 150MHz	9c	Mat	BC212, BC256, BCS56, 2SA933A..
2SB1653	Si-PNP	Sw, 400/400V, 0,5A, 1,5W, 20MHz	78	Mat	(2SA1156, 2SA1727, 2SA1772, 2SA1775)
2SB1655	Si-PNP	AF-Pow, 80V, 3A, 25W, 15MHz	17c	Rhm	BD938F, BDT32..F, 2SA1488A, 2SA1635,..
2SB1659	Si-PNP-Darl	AF, Sw-Pow, 110V, 6A, 50W, 100MHz, B>5000	17j$	Sak	-
2SB166	Ge-PNP	=2SB165: 0,18W	2ao	Nec	AC125..126, AC151..152, 2SB475
2SB1662	Si-PNP	AF, Sw-Pow, -/60V	17c	Mat	BD938F, BDT32AF..CF, 2SA1440..
2SB1663	Si-PNP	AF, Sw-Pow, 20V, 5A, 10W, 100MHz	30j$	Mat	2SA1242, 2SA1244, 2SA1385, 2SB967..
2SB1664	Si-PNP-Darl	Pow, 110/100V, 8A, 35W, >20MHz, B>1500	-	Sanyo	-
2SB1667	Si-PNP	AF, Sw-Pow, 60V, 3A, 25W, 9MHz	30j$	Tos	2SB1266, 2SB1268, 2SB1270, 2SB1449,..
2SB1668	Si-P-Darl+Di	AF, Sw-Pow, 100V, 8A, 30W, B=1k..20k	17c	Rhm	2SB1099, 2SB1228, 2SB1283, 2SB1431..
2SB167	Ge-PNP	AF, 20V, 0,5A, 0,2W	2a	Fui	AC128, AC153, AC188, 2SB405, 2SB415
2SB1672	Si-PNP	AF, Sw-Pow, 80V, 7A, 30W, 12MHz	17c	Rhm	2SA1442, 2SA1470, 2SA1742, 2SB1018
2SB1674	Si-P-Darl+Di	AF-Pow, 120V, 6A, 30W, 12MHz, B>2000	17c	Rhm	BD652F, 2SB1193, 2SB1340
2SB1675	Si-P-Darl+Di	AF-Pow, 80V, 10A, 30W, 12MHz, B>1000	17c	Rhm	BDT62AF, 2SB1100, 2SB1284, 2SB1551..
2SB1676	Si-P-Darl+Di	AF-Pow, 80V, 4A, 30W, 20MHz, B>1000	17c	Rhm	BDT60AF, 2SA1718, 2SB1258, 2SB1568..
2SB168	Ge-PNP	AF, 9V, 0,1A, 0,15W, B=60	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB169	Ge-PNP	=2SB168: a=85	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB1693	Si-P-Darl+Di	AF, Sw-Pow, Int. Z-Di, 60V, 3A	14h$	Nec	-
2SB16A	Ge-PNP	=2SB16: 20V	?2b	-	(AD162, 2SB493)
2SB17	Ge-PNP	AF, 32V, 0,6A, 1,8W	?2b	Fui	(AD162, 2SB493)
2SB170	Ge-PNP	AF, 30V, 0,1A, 0,125W, B>20	2a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB171	Ge-PNP	=2SB170: a>40	2a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB172	Ge-PNP	AF, 32V, 0,125A, 0,125W	2a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB173	Ge-PNP	AF, LN, 30V, 0,1A, 0,125W	2a	Mat	AC125..126, AC151r, ACY32, 2SB175
2SB174	Ge-PNP	AF, 20V, 0,3A, 0,225W	1a	Mat	AC128, AC152..153, AC188, 2SB405
2SB175	Ge-PNP	AF, 30V, 0,1A, 0,125W	2a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB176	Ge-PNP	AF, 32V, 0,125A, 0,125W	2a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB177	Ge-PNP	AF, 60V, 0,125A, 0,125W	2a	Mat	ACY24, ASY48, 2SB55
2SB178(Q)	Ge-PNP	AF, 20V, 0,3A, 0,225W	2a	Mat	AC128, AC152..153, AC188, 2SB405
2SB178A	Ge-PNP	=2SB178: 40V	2a	-	2N1189..90, 2SB405ST
2SB178B	Ge-PNP	=2SB178: 60V	2a	-	-
2SB179	Ge-PNP	AF, 25V, 0,05A, 0,08W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB17A	Ge-PNP	=2SB17: 40V	?2b	-	(2SB493)
2SB18	Ge-PNP	AF, 60V, 0,6A, 1,8W	?2b	Fui	-
2SB180	Ge-PNP	AF, 40V, 0,5A, 5,5W	2a	Fui	2SB493, (AD162)
2SB180A	Ge-PNP	=2SB180: 12W	2a	-	-
2SB181	Ge-PNP	=2SB180: 60V	2a	Fui	-
2SB181A	Ge-PNP	=2SB180: 60V, 12W	2a	-	-
2SB183	Ge-PNP	AF, 12V, 0,02A, 0,05W, B=55	37a	Hit	(AC125..126, AC151, 2SB54, 2SB56)

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2SB184	Ge-PNP	=2SB183: B=100	37a	Hit	(AC125..126,AC151,2SB54,2SB56)
2SB185	Ge-PNP	AF,25V,0,15A,0,2W,B>30	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB186(A,B)	Ge-PNP	=2SB185: a>100	2a	Sanyo	AC126,AC151,2SB54,2SB56
2SB187	Ge-PNP	AF,25V,0,15A,0,2W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB188	Ge-PNP	AF,25V,0,15A,0,2W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB189	Ge-PNP	AF-Dr/Out,25V,0,25A,0,25W	2ao	Tos	AC128K,AC153K,AC188K,2SB475
2SB1890	SI-PNP	-	39	Mat	→2SB1890
2SB18A	Ge-PNP	=2SB18: 80V	?2b	-	-
2SB19	Ge-PNP	AF-Pow,16V,2,5A,5,5W	-	Fui	(AD149,AUY19,2N2137,2N2142,..)
2SB190	Ge-PNP	AF,25V,0,05A,0,09W,B=150	2a	Oki	AC125..126,AC151,2SB54,2SB56
2SB191	Ge-PNP	=2SB190: a=70	2a	Oki	AC125..126,AC151,2SB54,2SB56
2SB192	Ge-PNP	=2SB190: a=35	2a	Oki	AC125..126,AC151,2SB54,2SB56
2SB193	Ge-PNP	=2SB190: 0,1A	2a$	Oki	AC125..126,AC151,2SB54,2SB56
2SB194	Ge-PNP	=2SB190: 0,1A, a=70	2a$	Oki	AC125..126,AC151,2SB54,2SB56
2SB195	Ge-PNP	=2SB190: 0,1A, a=35	2a$	Oki	AC125..126,AC151,2SB54,2SB56
2SB196	Ge-PNP	AF,Sw-Pow,30V,0,5A,0,5W	2a$	Oki	2SB493,(AD162)
2SB197	Ge-PNP	=2SB196: 50V	2a$	Oki	-
2SB198	Ge-PNP	=2SB196: 70V	2a$	Oki	-
2SB199	Ge-PNP	AF,12V,0,3A,0,25W	1a	Fui	AC128,AC152..153,AC188,2SB475
2SB20	Ge-PNP	=2SB19: 32V	-	Fui	(AD149,AUY19,2N2137,2N2142,..)
2SB200	Ge-PNP	AF-Dr/Out,32V,0,4A,0,25W	2a	Tos	AC128,AC153,AC188,2SB415
2SB200A	Ge-PNP	=2SB200: 45V	2a	-	2SB405ST
2SB201	Ge-PNP	AF-Dr/Out,35V,0,4A,0,3W,B>37	2a$	Tos	AC128,AC153,AC188,2SB415
2SB202	Ge-PNP	=2SB201: B>70	2a$	Tos	AC128,AC153,AC188,2SB415
2SB203	Ge-PNP	AF,Sw-Pow,40V,20A,80W	68a$	Shi	-
2SB204	Ge-PNP	AF,Sw-Pow,40V,30A,80W	68a$	Shi	-
2SB205	Ge-PNP	AF,Sw-Pow,80V,20A,80W	68a$	Shi	-
2SB206	Ge-PNP	AF,Sw-Pow,80V,30A,80W	68a$	Shi	-
2SB207	Ge-PNP	AF,Sw-Pow,100V,20A,80W	68a$	Shi	-
2SB207A	Ge-PNP	=2SB207: 140V	68a$	-	-
2SB208	Ge-PNP	AF,Sw-Pow,100V,30A,80W	68a$	Shi	-
2SB208A	Ge-PNP	=2SB208: 140V	68a$	-	-
2SB209	Ge-PNP	AF,Sw-Pow,40V,20A,80W	68a$	Shi	-
2SB21	Ge-PNP	=2SB19: 60V	-	Fui	(AD166,AUY19,2N2139,2N2144,..)
2SB210	Ge-PNP	AF,Sw-Pow,40V,30A,80W	68a$	Shi	-
2SB211	Ge-PNP	AF,Sw-Pow,80V,20A,80W	68a$	Shi	-
2SB212	Ge-PNP	AF,Sw-Pow,80V,30A,80W	68a$	Shi	-
2SB213	Ge-PNP	AF,Sw-Pow,100V,20A,80W	68a$	Shi	-
2SB213A	Ge-PNP	=2SB213: 140V	68a$	-	-
2SB214	Ge-PNP	AF,Sw-Pow,100V,30A,80W	68a$	Shi	-
2SB214A	Ge-PNP	=2SB214: 140V	68a$	-	-
2SB215	Ge-PNP	AF,Sw-Pow,100V,3A,24W	23a$	Sanyo	AL102..103,2N1542,2N1547,2SB231..
2SB216(A)	Ge-PNP	=2SB215: 60V	23a$	Sanyo	AD149,2N1540,2N1545,2SB449..
2SB217	Ge-PNP	=2SB215: 25V	23a$	Sanyo	AD149,2N1539,2N1544,2SB449..
2SB218	Ge-PNP	AF,Sw,80V,0,1A,0,225W	2a&	Nec	ACY39,2N2042..43
2SB219	Ge-PNP	AF-Dr/Out,30V,0,2A,0,225W,B>19	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB219A	Ge-PNP	=2SB219: 0,5A	2a&	-	AC128,AC152..153,AC188,2SB415
2SB22	Ge-PNP	AF-Dr/Out,25V,0,2A,0,3W	2ao	Sanyo	AC128(K),AC151..153,AC188(K),2SB405
2SB220	Ge-PNP	=2SB219: B>34	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB220A	Ge-PNP	=2SB219: 0,5A, B>34	2a&	-	AC128,AC152..153,AC188,2SB415
2SB221	Ge-PNP	=2SB219: B>53	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB221A	Ge-PNP	=2SB219: 0,5A, B>53	2a&	-	AC128,AC152..153,AC188,2SB415
2SB222	Ge-PNP	=2SB219: B>72	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB222A	Ge-PNP	=2SB219: 0,5A, B>72	2a&	-	AC128,AC152..153,AC188,2SB415
2SB223	Ge-PNP	=2SB219: B>99	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB223A	Ge-PNP	=2SB219: 0,5A, B>99	2a&	-	AC128,AC152..153,AC188,2SB415
2SB224	Ge-PNP	AF,45V,0,5A,0,225W,B>19	2a&	Nec	2N1189..1190,2SB405ST
2SB225	Ge-PNP	=2SB224: B>34	2a&	Nec	2N1189..1190,2SB405ST
2SB226	Ge-PNP	=2SB224: B>53	2a&	Nec	2N1189..1190,2SB405ST
2SB227	Ge-PNP	=2SB224: B>72	2a&	Nec	2N1189..1190,2SB405ST
2SB228	Ge-PNP	AF,Sw-Pow,80V,5A,50W	23a$	Hit	AL102..103,2N1541,2N1546,2SB231..
2SB229	Ge-PNP	=2SB228: 100V	23a$	Hit	AL102..103,2N1542,2N1547,2SB231..
2SB23	Ge-PNP	AF,15V,0,01A,0,04W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB230	Ge-PNP	=2SB228: 120V	23a$	Hit	AL102,2N1543,2N1548,2SB231..

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2SB231	Ge-PNP	Sw,Pow,TV-HD,120V,6A,25W	23a$	Toshiba	AL102,AU110,AU210,2N5324
2SB232	Ge-PNP	Sw,Pow,130V,6A,54W,B>20	23a$	Matsushita	AL102,AU110,AU210,2N5324,2SB231
2SB233	Ge-PNP	=2SB232:B>100	23a$	Mat	AL102,AU110,AU210,2N5324,2SB231
2SB234	Ge-PNP	=2SB232:180V,B>15	23a$	Mat	AU107,AU113,AU213,2N5324
2SB235	Ge-PNP	Sw,Pow,80V,15A,60W	38a$	Tos	2N1982,2N2075,2N2079,2N2492..93..
2SB236	Ge-PNP	=2SB235:60V	38a$	Tos	2N1981,2N2076,2N2080,2N2490..91..
2SB237	Ge-PNP	=2SB235:36V	38a$	Tos	2N1980,2N2077,2N2081,2N2490..91..
2SB238	Ge-PNP	AF,Sw-Pow,40V,1A,13W	2a$	Nec	2SB493,(AD162)
2SB239	Ge-PNP	=2B238:80V	2a$	Nec	-
2SB239A	Ge-PNP	=2B238:100V	2a$	-	-
2SB24	Ge-PNP	AF,15V,0,015A,0,1W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB240	Ge-PNP	AF,Sw-Pow,40V,1A,13W	2a$	Nec	2SB493,(AD162)
2SB240A	Ge-PNP	=2B240:60V	2a$	-	-
2SB241(N)	Ge-PNP	=2SB240:80V	2a$	Nec	-
2SB241A(AN)	Ge-PNP	=2B241:100V	2a$	-	-
2SB242	Ge-PNP	AF,Sw-Pow,30V,1A,13W	2a$	Nec	2SB493,(AD162)
2SB242A	Ge-PNP	=2B242:60V	2a$	-	-
2SB243	Ge-PNP	AF,Sw-Pow,30V,1A,13W	2a$	Nec	2SB493,(AD162)
2SB243A	Ge-PNP	=2SB243:60V	2a$	-	-
2SB244	Ge-PNP	AF,Sw-Pow,80V,1A,13W	2a$	Nec	-
2SB245	Ge-PNP	AF,Sw-Pow,80V,1A,13W	2a$	Nec	-
2SB246	Ge-PNP	AF,Sw-Pow,40V,5A,54W	23a$	Nec	AL102..103,2N1539,2N1544,2SB231..
2SB247	Ge-PNP	=2SB246:60V	23a$	Nec	AL102..103,2N1540,2N1545,2SB231..
2SB248	Ge-PNP	AF,Sw-Pow,40V,5A,54W	23a$	Nec	AL102..103,2N1539,2N1544,2SB231..
2SB248A	Ge-PNP	=2SB248:60V	23a$	-	AL102..103,2N1540,2N1545,2SB231..
2SB249	Ge-PNP	AF,Sw-Pow,80V,5A,54W	23a$	Nec	AL102..103,2N1541,2N1546,2SB231..
2SB25(N)	Ge-PNP	AF,Sw-Pow,60V,1,5A,20W	23a$	Tos	AD166,AUY19,2N2139,2N2144..
2SB250	Ge-PNP	AF,Sw-Pow,30V,5A,54W	23a$	Nec	AL102..103,2N1539,2N1544,2SB231..
2SB250A	Ge-PNP	=2SB250:60V	23a$	-	AL102..103,2N1540,2N1545,2SB231..
2SB251	Ge-PNP	AF,Sw-Pow,30V,5A,54W	23a$	Nec	AL102..103,2N1539,2N1544,2SB231..
2SB251A	Ge-PNP	=2SB251:60V	23a$	-	AL102..103,2N1540,2N1545,2SB231..
2SB252	Ge-PNP	AF,Sw-Pow,80V,5A,54W	23a$	Nec	AL102..103,2N1541,2N1546,2SB231..
2SB252A	Ge-PNP	=2SB252:120V	23a$	-	AL102,2N1543,2N1548,2SB231..
2SB253	Ge-PNP	AF,Sw-Pow,80V,5A,54W	23a$	Nec	AL102..103,2N1541,2N1546,2SB231..
2SB253A	Ge-PNP	=2SB253:120V	23a$	-	AL102,2N1543,2N1548,2SB231..
2SB254	Ge-PNP	AF,Sw-Pow,35V,1A,12W	22a$	Sanyo	AD162,2SB474,2SB481
2SB255	Ge-PNP	AF,Sw-Pow,35V,1A,12W	22a$	Sanyo	AD162,2SB474,2SB481
2SB256	Ge-PNP	AF,Sw-Pow,25V,1A,12W	22a$	Sanyo	AD162,2SB474,2SB481
2SB257	Ge-PNP	AF,LN,18V,0,04A,0,06W	2a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB258	Ge-PNP	Sw,Pow,120V,15A,60W	38a$	Tos	-
2SB259	Ge-PNP	=2SB258:80V	38a$	Tos	2N1982,2N2075,2N2079,2N2492..
2SB26	Ge-PNP	AF,Sw-Pow,32V,1,5A,20W	23a$	Tos	AD149,AUY19,2N2137,2N2142..
2SB260	Ge-PNP	=2SB258:50V	38a$	Tos	2N1980,2N2077,2N2081,2N2491..
2SB261	Ge-PNP	AF,20V,0,03A,0,065W,B=45	37a	Fui	(AC125..126,AC151,2SB54,2SB56)
2SB262	Ge-PNP	=2SB261:a=90	37a	Fui	(AC125..126,AC151,2SB54,2SB56)
2SB263	Ge-PNP	AF,20V,0,15A,0,2W	2a	Fui	AC125..126,AC151,2SB54,2SB56
2SB264	Ge-PNP	AF,LN,30V,0,05A,0,07W	2a	Nec	AC125..126,AC151r,ACY32,2SB173
2SB265	Ge-PNP	AF,Sw,40V,0,1A,0,17W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB266	Ge-PNP	AF,25V,0,15A,0,15W,B=67	2a	old	AC125..126,AC151,2SB54,2SB56
2SB267	Ge-PNP	=2SB266:B=70	2a	old	AC125..126,AC151,2SB54,2SB56
2SB268	Ge-PNP	AF,30V,0,15A,0,25W	1a	Mit	AC128,AC152..153,AC188,2SB475
2SB269	Ge-PNP	AF,LN,25V,0,15A,0,15W	2a	old	AC125..126,AC151r,ACY32,2SB173
2SB26A	Ge-PNP	=2SB26:60V	23a$	-	AD166,AUY19,2N2139,2N2144..
2SB27	Ge-PNP	AF,Sw-Pow,15V,0,5A,5W,B>18	23a$	Son	AD149,AUY19,2N2137,2N2142,2SB449..
2SB270	Ge-PNP	AF,12V,0,15W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB271	Ge-PNP	AF,25V,0,5A,0,72W,B=80	2a	Sanyo	AC128,AC153,AC188,2SB405,2SB415
2SB272	Ge-PNP	=2SB271:B=100	2a	Sanyo	AC128,AC153,AC188,2SB405,2SB415
2SB273	Ge-PNP	=2SB271:35V,B=100	2a	Sanyo	AC128,AC153,AC188,2SB405,2SB415
2SB274	Ge-PNP	AF,Sw-Pow,80V,6A,50W	23a$	Hit	AL102..103,2N3615,2N3617,2N2526..
2SB275	Ge-PNP	=2SB274:120V	23a$	Hit	AL102,2N2290,2N2293,2N2527..
2SB276	Ge-PNP	=2SB274:120V,10A	23a$	Hit	AL100,2N2290,2N2293,2N2527..
2SB277	Ge-PNP	AF,15V,5mA,0,08W	1a	Mat	AC125..126,AC151,2SB54,2SB56
2SB278	Si-PNP	AF,Hi-Ueb,25V,0,05A,0,25W,a=28	1a	Mat	2SA1252,2SB902,(BC558,..)
2SB279	Si-PNP	=2SB278:a=50	1a	Mat	2SA1252,2SB902,(BC558,..)

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2SB28	Ge-PNP	=2B27: B>35	23a$	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449..
2SB280	Si-PNP	AF, 32V, 0,25A, 0,3W	1a	Mat	BC213, BC258, BC308, BC558, 2SA953..
2SB281	Si-PNP	=2SB280: 60V	1a	Mat	BC212, BC256, BC266, BC556, 2SA953..
2SB282	Ge-PNP	AF, Sw-Pow, 80V, 6A, 30W, B>15	23a$	Mat	AL102..103, AUY22, 2N3615, 2N3617..
2SB283	Ge-PNP	=2SB282: 60V, B>35	23a$	Mat	AL102..103, AUY21, 2N3612, 2N3614..
2SB284	Ge-PNP	=2SB282: 60V, B>20	23a$	Mat	AL102..103, AUY21, 2N3612, 2N3614..
2SB285	Ge-PNP	=2SB282: B>20	23a$	Mat	AL102..103, AUY22, 2N3615, 2N3617..
2SB286	Ge-PNP	AF, Sw-Pow, 80V, 6A, 43W, B=17	23a$	Mat	AL102..103, AUY22, 2N3615, 2N3617..
2SB287	Ge-PNP	=2SB286: B=36	23a$	Mat	AL102..103, AUY22, 2N3615, 2N3617..
2SB288	Ge-PNP	AF, 32V, 0, 125A, 0, 125W	2a	Mat	AC125..126, AC151..152, 2SB475
2SB289	Ge-PNP	=2SB288: 60V	2a	Mat	ACY24, ASY48, ASY77, 2SB55
2SB29	Ge-PNP	=2B27: B>72	23a$	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449..
2SB290	Ge-PNP	AF, LN, 18V, 0,04A, 0,065W	2a	Tos	AC125..126, AC151r, ACY32, 2SB173
2SB291	Ge-PNP	AF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB292	Ge-PNP	AF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB292A	Ge-PNP	=2SB292: 60V	2a	-	ACY24, ASY48, ASY77, 2SB55
2SB293	Ge-PNP	AF, 18, 0,25A, 0,15W, B=70	2a	old	AC128, AC152..153, AC188, 2SB475
2SB294	Ge-PNP	=2SB293: a=36	2a	old	AC128, AC152..153, AC188, 2SB475
2SB295	Ge-PNP	AF, Sw-Pow, 100V, 5A, 40W	23a$	Fui	AL102..103, 2N3616, 2N3618, 2N2527..
2SB296	Ge-PNP	Sw, Pow, TV-HD, 130V, 10A, 35W	23a$	Toshiba	AU110, AU210
2SB299	Ge-PNP	AF, Sw, 30V, Ueb=25V, 0,15A, 0,15W	2a	old	AC125..126, AC151, ASY26, ASY76..77
2SB30	Ge-PNP	=2B27: gep., B=68	23a$	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449..
2SB300	Ge-PNP	AF, Sw-Pow, 100V, 10A, 35W	23a$	Tos	AL100..101, 2N2290, 2N2293, 2N2527..
2SB301	Ge-PNP	=2SB300: 60V	23a$	Tos	AL100..101, 2N2289, 2N2292, 2N2526..
2SB302	Ge-PNP	AF, LN, 10V, 2mA, 0,04A	2a	Hit	AC125..126, AC151r, ACY32, 2SB173
2SB303	Ge-PNP	AF, LN, 25V, 0,02A, 0,1W	2a	Sanyo	AC125..126, AC151r, ACY32, 2SB173
2SB304	Ge-PNP	AF, Sw, 30V, 0,5A, 0,225W	2a	Fui	AC128, AC153, AC188, 2SB324, 2SB415
2SB304A	Ge-PNP	=2SB304: 45V	2a	-	ACY24, ASY48, ASY76..77, 2N1189..90
2SB306	Ge-PNP	AF, Sw, 105V, 0,02A, 0,075W	2a	Tos	ACY39, 2N2042..2043
2SB309(A)	Ge-PNP	AF, Sw-Pow, 75V, 8A, 43W	23a$	Mat	AL100..101, 2N2289, 2N2292, 2N2526..
2SB31	Ge-PNP	=2B27: gep., B=115	23a$	Son	AD149, AUY19, 2N2137, 2N2142, 2SB449..
2SB310	Ge-PNP	=2SB309: 140V	23a$	Mat	AU110, AU210, 2N2528
2SB311	Ge-PNP	=2SB309: 180V, 10A	23a$	Mat	AU107, AU113, AU213, 2N5324
2SB312	Ge-PNP	=2SB309: 140V	23a$	Mat	AU110, AU210, 2N2528
2SB313	Ge-PNP	=2SB309: 180V, 10A	23a$	Mat	AU107, AU113, AU213, 2N5324
2SB314	Ge-PNP	AF, Sw, 30V, 0,5A, 3W	?2b$o	Oki	2SB493, (AD162)
2SB315	Ge-PNP	AF, 16V, 0,3A, 0,15W, B=50	2a	Mit	AC128, AC152..153, AC188, 2SB475
2SB316	Ge-PNP	=2SB315: B=60	2a	Mit	AC128, AC152..153, AC188, 2SB475
2SB317	Ge-PNP	=2SB315: 0,25W, B=60	1a	Mit	AC128, AC152..153, AC188, 2SB475
2SB318	Ge-PNP	AF, Sw-Pow, 60V, 5A, 50W	23a$	Fui	AL102..103, 2N1540, 2N1545, 2N2526..
2SB319	Ge-PNP	=2SB318: 100V	23a$	Fui	AL102..103, 2N1542, 2N1547, 2N2527..
2SB32	Ge-PNP	AF, 20V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB320	Ge-PNP	=2SB318: 100V, 10A	23a$	Fui	AL100..101, 2N2290, 2N2293, 2N2527..
2SB321	Ge-PNP	=2SB322: ra, a=100	37a	Tos	(AC125..126, AC151r, ACY32, 2SB173)
2SB322	Ge-PNP	Min, AF, 12V, 0,05A, 0,04W, a=50	37a	Tos	(AC125..126, AC151, 2SB54, 2SB56)
2SB323	Ge-PNP	=2SB322: a=100	37a	Tos	(AC125..126, AC151, 2SB54, 2SB56)
2SB324	Ge-PNP	AF, 32V, 1A, 0,22W	2a	Mat	AC128, AC153, AC188, 2SB415
2SB325	Ge-PNP	Sw, Pow, 120V, 0,6A, 1,8W	?2a	Fui	-
2SB326	Ge-PNP	AF, Sw, 30V, Ueb=15V, 0,5A, 0,225W, B>45	2a&	Nec	AC128, AC153, AC188, ASY76..77
2SB327	Ge-PNP	=2SB326: B>70	2a&	Nec	AC128, AC153, AC188, ASY76..77
2SB328	Ge-PNP	AF, Sw, 25V, 0,2A, 0,15W, B>40	2a	Nec	AC125..126, AC151..152, ASY26..27
2SB329	Ge-PNP	=2SB328: B>85	2a	Nec	AC125..126, AC151..152, ASY26..27
2SB33	Ge-PNP	AF, 20V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB330	Ge-PNP	AF, Sw, 110V, 0,15A, 0,225W	2a&	Nec	ACY39, 2N2042..2043
2SB331(H)	Ge-PNP	Sw, Pow, 40V, 15A, 80W	38a$	Hit	2N1980, 2N2078, 2N2082, 2N2491..
2SB332(H)	Ge-PNP	=2SB331: 60V	38a$	Hit	2N1981, 2N2076, 2N2080, 2N2491..
2SB333(H)	Ge-PNP	=2SB331: 80V	38a$	Hit	2N1982, 2N2075, 2N2079, 2N2492..
2SB334(H)	Ge-PNP	=2SB331: 100V	38a$	Hit	2N2493
2SB335	Ge-PNP	Min, AF, 20V, 0,06A, 0,083W, B=60	37a	Mat	(AC125..126, AC151, 2SB54, 2SB56)
2SB336	Ge-PNP	=2SB335: B=120	37a	Mat	(AC125..126, AC151, 2SB54, 2SB56)
2SB337(H)	Ge-PNP	AF, Sw-Pow, 50/40V, 7A, 30W	23a$	Hit	AL102..103, AUY22, 2N3611, 2N3613..
2SB338(H)	Ge-PNP	=2SB337: 60V	23a$	Hit	AL102..103, AUY22, 2N3612, 2N3614..
2SB339(H)	Ge-PNP	AF, Sw-Pow, 80V, 10A, 44W	23a$	Hit	AL100..101, 2N2289, 2N2292, 2N2526..
2SB34	Ge-PNP	AF, 20V, 0,15A, 0,25W	1a	Fui	AC125..126, AC151, 2SB54, 2SB56

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2SB340(H)	Ge-PNP	=2SB339:100V	23a$	Hit	AL100..101,2N2290,2N2293,2N2527..
2SB341(H)	Ge-PNP	=2SB339:120V	23a$	Hit	AL100..101,2N2290,2N2293,2N2527..
2SB342	Ge-PNP	AF,Sw-Pow,120V,6A,30W	23a$	Sanyo	AU110,AU210,2N2527..2528
2SB343	Ge-PNP	=2SB342:150V	23a$	-	AU107,AU110,2N2528
2SB345	Ge-PNP	AF,32V,0,1A,0,165W,B>65	2a	Mat	AC125..126,AC151,2SB54,2SB56
2SB346	Ge-PNP	=2SB345:a>80	2a	Mat	AC125..126,AC151,2SB54,2SB56
2SB347	Ge-PNP	=2SB345:ra	2a	Mat	AC125..126,AC151r,ACY32,2SB173
2SB348	Ge-PNP	=2SB345:ra,a>80	2a	Mat	AC125..126,AC151r,ACY32,2SB173
2SB349	Ge-PNP	AF,20V,0,01A,0,05W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB350	Ge-PNP	AF,25V,0,05A,0,15W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB351	Ge-PNP	Sw,Pow,40V,15A,70W	38a$	Fui	2N1980,2N2078,2N2082,2N2491
2SB352	Ge-PNP	=2SB351:60V	38a$	Fui	2N1981,2N2076,2N2080,2N2492
2SB353	Ge-PNP	=2SB351:80V	38a$	Fui	2N1982,2N2075,2N2079,2N2492
2SB354	Ge-PNP	=2SB351:100V	38a$	Fui	2N2493
2SB355	Ge-PNP	AF,Sw-Pow,25V,1A,15W	22a$	Mit	AD162,2SB474,2SB481
2SB356	Ge-PNP	=2SB355:80V	22a$	Mit	-
2SB357	Ge-PNP	=2SB355:100V	22a$	Mit	-
2SB358	Ge-PNP	AF,Sw-Pow,80V,6A,50W	23a$	Mit	AL102..103,2N3615,2N3617,2N2526..
2SB359	Ge-PNP	=2SB358:120V,10A	23a$	Mit	AL100,2N2290,2N2293,2N2527..
2SB360	Ge-PNP	=2SB358:180V,10A	23a$	Mit	AU107,AU113,AU213,2N5324
2SB361(H)	Ge-PNP	AF,Sw-Pow,80V,5A,40W	23a$	Hit	AL102..103,AUY22,2N1541,2N1546..
2SB362(H)	Ge-PNP	AF,Sw-Pow,100V,7A,50W	23a$	Hit	AL102..103,2N3616,2N3618,2N2527..
2SB363	Ge-PNP	AF,Sw-Pow,140V,8A,43W	23a$	Nec	AU107,AU110,AU210,2N2528
2SB364	Ge-PNP	AF,20V,0,4A,Q,15W,B>60	2a	Tos	AC128,AC153,AC188,2SB475
2SB365	Ge-PNP	=2SB364:B>35	2a	Tis	AC128,AC153,AC188,2SB475
2SB366	Ge-PNP	AF,Sw-Pow,140V,8A,43W	23a$	Tos	AU107,AU110,AU210,2N2528
2SB367(H)	Ge-PNP	AF-Pow,25V,1A,6,6W	22a$	Hit	AD162,2SB474,2SB481
2SB368(H)	Ge-PNP	=2SB367:45V	22a$	Hit	-
2SB37	Ge-PNP	AF,30V,0,05A,0,15W	2a	Fui	AC125..126,AC151,2SB54,2SB56
2SB370(H)	Ge-PNP	AF,25V,0,5A,0,2W	2a	Hit	AC128,AC153,AC188,2SB405,2SB475
2SB370A(AH)	Ge-PNP	=2SB370:32V	2a	Hit	AC128,AC153,2SB415,2SB475
2SB371	Ge-PNP	AF,32V,0,2A,0,165W	2a	Mat	AC125..126,AC151..152,2SB475
2SB372	Ge-PNP	AF,25V,1A,1,5W,B=70	2a	Sanyo	AC128,AC153,AC188,2SB405,2SB415
2SB373	Ge-PNP	=2SB372:B=150	2a	Sanyo	AC128,AC153,AC188,2SB405,2SB415
2SB374	Ge-PNP	=2SB372:60V,B=150	2a	Sanyo	2N1039,2N2565
2SB375(A)	Ge-PNP	Sw,Pow,150V,9A,30W	23a$	Sanyo	AU107,AU110,AU113,AU213,2N5324
2SB376	Ge-PNP	AF,20V,0,3A,0,225W	2a	Mat	AC128,AC152..153,AC188,2SB475
2SB377	Ge-PNP	AF,LN,32V,0,15A,0,27W	2a&	Son	AC125..126,AC151r,ACY32,2SB173
2SB378	Ge-PNP	AF,18V,0,15A,0,18W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB378A,B	Ge-PNP	=2SB378:23V,0,3..0,5A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB379	Ge-PNP	AF,18V,0,15A,0,18W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB379A,B	Ge-PNP	=2SB379:23V,0,3..0,5A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB38	Ge-PNP	AF,30V,0,15A,0,25W	1a	Fui	AC125..126,AC151,2SB54,2SB56
2SB380	Ge-PNP	AF,18V,0,15A,0,18W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB380A,B	Ge-PNP	=2SB380:23V,0,3..0,5A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB381	Ge-PNP	AF,32V,0,3A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB382	Ge-PNP	AF,32V,0,3A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB383	Ge-PNP	AF,32V,0,5A,0,27W	2a&	Son	AC128,AC152..153,AC188,2SB475
2SB384	Ge-PNP	AF,20V,0,03A,0,08W,B=60	2a	old	AC125..126,AC151,2SB54,2SB56
2SB385	Ge-PNP	=2SB384:B=50	2a	old	AC125..126,AC151,2SB54,2SB56
2SB386	Ge-PNP	AF,Sw,30V,0,3A,0,15W	2a	Mit	AC128,AC152..153,AC188,ASY26
2SB387	Ge-PNP	Min,AF,12V,0,02A,0,03W	37a	Hit	(AC125..126,AC151,2SB54,2SB56)
2SB389	Ge-PNP	AF,LN,12V,0,01A,0,08W	2a	Fui	AC125..126,AC151r,ACY32,2SB173
2SB39	Ge-PNP	AF,LN,10V,2mA,0,05W	2a	Fui	AC125..126,AC151r,ACY32,2SB173
2SB390	Ge-PNP	AF,Sw-Pow,80V,6A,30W	23a$	Sanyo	AL102..103,AUY22,2N3615,2N3617..
2SB391	Ge-PNP	=2SB390:50V	23a$	Sanyo	AL102..103,AUY22,2N3612,2N3614..
2SB392	Ge-PNP	AF,Sw,20V,0,2A,0,2W	2a	Oki	AC125..126,AC151..152,ASY26..27
2SB393	Ge-PNP	AF,Sw,28V,0,2A,0,2W	2a	Oki	AC125..126,AC151..152,ASY26..27
2SB394	Ge-PNP	AF,Sw,28V,0,2A,0,2W	2a	Oki	AC125..126,AC151..152,ASY26..27
2SB395	Ge-PNP	AF,Sw,28V,0,2A,0,2W	2a	Oki	AC125..126,AC151..152,ASY26..27
2SB396	Ge-PNP	AF,Sw,40V,0,2A,0,15W	2a	Oki	ASY48,ASY76..77,2N1191..94
2SB397	Ge-PNP	AF,Sw,48V,0,08A,0,2W	2a	Oki	ASY48,ASY77,2N1191..94
2SB398	Ge-PNP	AF,Sw,110V,0,08A,0,2W	2a	Oki	ACY39,2N2042..2043
2SB399	Ge-PNP	AF,Sw,110V,0,08A,0,2W	2a	Oki	ACY39,2N2042..2043

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2SB40	Ge-PNP	AF,Sw,40V,0,1A,0,08W	2a	Tos	ASY48,ASY76..77,2SB177
2SB400	Ge-PNP	AF,LN,20V,0,04A,0,1W	2a	Sanyo	AC125..126,AC151r,ACY32,2SB173
2SB401	Ge-PNP	AF,Sw,40V,0,3A,0,24W	2a	Mat	ACY24,ASY48,ASY76..77
2SB402	Ge-PNP	=2SB401:60V	2a	-	ACY24,ASY48,ASY77
2SB403	Ge-PNP	AF,Sw,40V,0,3A,0,24W	2a	Mat	ACY24,ASY48,ASY76..77
2SB404	Ge-PNP	AF,Sw,100V,0,1A,0,1W	2a	Sanyo	ACY39,2N2042..43
2SB405	Ge-PNP	AF,25V,1A,0,21W	2a	Sanyo	AC128,AC153,AC188,2SB415
2SB405K	Ge-PNP	=2SB405:	3a	-	AC128K,AC153K,AC188K
2SB405ST	Ge-PNP	=2SB405:40V	2a	-	-
2SB406	Ge-PNP	Sw,Pow,200/100V,10A,37,5W	23a$	Sanyo	AU107,AU113,AU213,2N5324
2SB407	Ge-PNP	AF,Sw-Pow,30V,7A,30W	23a$	Sanyo	AL102..AL103,AUY22,2N3611,2N3613..
2SB408	Ge-PNP	AF,25V,0,2A,0,3W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB409	Ge-PNP	AF,12V,0,08A,0,15W	2a	Sanyo	AC125..126,AC151,2SB54,2SB56
2SB41	Ge-PNP	AF,Sw-Pow,40V,1,2A,44W	23a$	Fui	AD149,AUY19,2N2138,2N2143,2SB449..
2SB410	Ge-PNP	Sw,Pow,TV-HD,135V,15A,40W	23a$	Sanyo	AU107,AU110,AU210
2SB411	Ge-PNP	Sw,Pow,TV-HD,200V,11A,40W	23a$	Sanyo	AU107,AU113,AU213,2N5324
2SB412	Ge-PNP	Sw,Pow,TV-HD,300V,11A,40W	23a$	Sanyo	AU106,AU109,AU111,AU112,2N5325
2SB413	Ge-PNP	AF,Sw-Pow,60V,1,5A,12,5W	22a$	Tos	-
2SB414	Ge-PNP	=2SB413:32V	22a$	Tos	AD162,2SB474,2SB481
2SB415	Ge-PNP	AF,32V,1A,0,2W	2a	Tos	AC128,AC153,AC188,2SB324
2SB416	Ge-PNP	AF,25V,0,08A,0,15W	2a	Oki	AC125..126,AC151,2SB54,2SB56
2SB417	Ge-PNP	=2SB416:45V	2a	Oki	ACY24,ASY48,ASY77,2N1191..91
2SB418	Ge-PNP	=2SB416:70V	2a	Oki	ACY24,ASY48,ASY77,2N2042..43
2SB419(H)	Ge-PNP	AF,Sw-Pow,45V,1,5A,6W	22a$	Hit	-
2SB42	Ge-PNP	=2SB41:60V	23a$	Fui	AD166,AUY19,2N2139,2N2144..
2SB420	Ge-PNP	AF,Sw-Pow,120V,1,5A,6W	22a$	Hit	-
2SB421	Ge-PNP	AF,Sw,80V,0,6A,0,3W	2a	Tos	ACY39,2N2042..2043
2SB422	Ge-PNP	AF,18V,0,04A,0,06W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB423	Ge-PNP	AF,30V,0,15A,0,15W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB424	Ge-PNP	AF,Sw-Pow,80V,3A,30W	23a$	Tos	AUY20,2N1541,2N1546,2N2141,2N2146..
2SB425	Ge-PNP	=2SB424:60V	23a$	Tos	AUY19,2N1540,2N1545,2N2139,2N2144..
2SB426	Ge-PNP	AF,Sw-Pow,32V,3A,30W	23a$	Tos	AUY19,2N1539,2N1544,2N2137,2N2142..
2SB426A	Ge-PNP	=2SB426:45V	23a$	Tos	AUY19,2N1539,2N1544,2N2138,2N2143..
2SB427	Ge-PNP	AF,Sw,45V,0,5A,0,225A,B=60	2a	Fui	2N1189..90,2SB405ST
2SB428	Ge-PNP	=2SB427:B=90	2a	Fui	2N1189..90,2SB405ST
2SB429	Ge-PNP	AF,30V,0,05A,0,1W	2a	Nec	AC125..126,AC151,2SB54,2SB56
2SB43	Ge-PNP	AF,25V,0,05A,0,15W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB430	Ge-PNP	Sw,Pow,70V,20A,80W	38a$	Mat	2N1519,2N1521,2N1523
2SB431	Ge-PNP	AF,32V,0,5A,0,2W	2a	Fui	AC128,AC153,AC188,2SB324,2SB415
2SB432	Ge-PNP	AF,Sw-Pow,150V,5A,50W	23a$	Fui	AU107,AU110,2N2528
2SB433(F)	Ge-PNP	AF,Sw-Pow,70V,15A,56W	38a$	Fui	2N1981,2N2076,2N2080,2N2490
2SB434	Si-PNP	AF-Pow,50V,3A,25W,10MHz	17j$	Tos,Mic	BD242,BD244B,BD540A,BD536,BD936..
2SB435	Si-PNP	=2SB434:40V	17j$	Tos,Mic	BD242,BD244B,BD540,BD534,BD934..
2SB436	Ge-PNP	AF,25V,0,12A,0,12W	2a	Oki	AC125..126,AC151,2SB54,2SB56
2SB437	Ge-PNP	=2SB436:45V	2a	Oki	ACY24,ASY48,ASY76..77,2N1191..94
2SB438	Ge-PNP	=2SB436:70V	2a	Oki	ACY24,ASY48,ASY76..77
2SB439	Ge-PNP	AF,LN,30V,0,15A,0,15W	2a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB43A	Ge-PNP	=2SA43:45V,0,15A	2a	-	ACY24,ASY48,2SB55,2SB56A
2SB44	Ge-PNP	AF,30V,0,05A,0,08W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB440	Ge-PNP	AF,LN,30V,0,15A,0,15W	2a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB441	Ge-PNP	Sw,Pow,160/45V,6A,40W	23a$	Hitachi	AU107,AU110,2N2528
2SB442(H)	Ge-PNP	Sw,Pow,160/60(H=/80)V,6A,40W	23a$	Hitachi	AU107,AU110,2N2528
2SB443	Ge-PNP	AF,LN,18V,0,01A,0,1W	2a	Hit	AC125..126,AC151r,ACY32,2SB173
2SB444	Ge-PNP	AF,LN,18V,0,01A,0,1W	2a	Hit	AC125..126,AC151r,ACY32,2SB173
2SB445	Ge-PNP	AF,Sw-Pow,40V,1,5A,10W	22a$	Fui	AD162,2SB474,2SB481
2SB446	Ge-PNP	=2SB445:60V	22a$	-	-
2SB447	Ge-PNP	Sw,Pow,220V,6A,45W	23a$	Fujitsu	AU113,AU213,2N5324
2SB448	Ge-PNP	AF,Sw-Pow,32V,1A,13W	22a$	Mat	AD162,2SB474,2SB481
2SB449	Ge-PNP	AF,Sw-Pow,50V,3,5A,22,5W(Tc=50°)	23a$	Mat	AD149,AD166..167,AUY28,2N1540..
2SB450	Ge-PNP	AF,25V,0,5A,0,2W	2a	Mit	AC128,AC153,AC188,2SB324,2SB415
2SB450A	Ge-PNP	=2SB450:32V	2a	Mit	AC128,AC153,2SB324,2SB415
2SB451	Ge-PNP	AF-Dr/Out,25V,1A,0,3W,B=80	2a	Mit	AC128,AC153,AC188,2SB324,2SB415
2SB452	Ge-PNP	=2SB451:B=150	2a	Mit	AC128,AC153,AC188,2SB324,2SB415
2SB452A	Ge-PNP	=2SB451:32V	2a	-	AC128,AC153,2SB324,2SB415

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2SB453	Ge-PNP	AF,Sw,30V,0,3A,0,25W	2a	Mit	AC128,AC153,AC188,A5Y48,2SB475
2SB454	Ge-PNP	=2SB453:80V	2a	Mit	ACY39,2N2042..2043
2SB455	Ge-PNP	=2SB453:105V	2a	Mit	ACY39,2N2042..2043
2SB456	Ge-PNP	AF,Sw-Pow,80V,1A,13W	2a$	Fui	-
2SB457	Ge-PNP	AF,20V,0,5A,0,15W	2a	Mit	AC128,AC153,AC188,2SB415,2SB475
2SB457A	Ge-PNP	=2SB457:32V	2a	-	AC128,AC153,2SB324,2SB415
2SB458	Ge-PNP	AF,Sw-Pow,25V,1A,4W	22a$	Mit	AD162,2SB474,2SB481
2SB458A	Ge-PNP	=2SB458:45V	22a$	-	-
2SB458B	Ge-PNP	=2SB458:100V	22a$	-	-
2SB459	Ge-PNP	AF,LN,30V,0,05A,0,12W	2a	Hit	AC125..126,AC151r,ACY32,2SB173
2SB46	Ge-PNP	AF,25V,0,05A,0,08W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB460	Ge-PNP	=2SB459:40V	2a	Hit	AC125..126,AC151r,ACY32,2SB173
2SB461	Ge-PNP	AF-Dr/Out,35V,1A,0,25W	2a$	Tos	AC128,AC153,AC188,2SB324,2SB415
2SB462	Ge-PNP	AF,Sw-Pow,60V,2A,6W	22a$	Tos	-
2SB463	Ge-PNP	=2SB462:32V	22a$	Tos	AD162,2SB474,2SB481
2SB464	Ge-PNP	AF,Sw-Pow,100V,6A,30W	23a$	Tos	AL102..103,2N3616,2N3618,2N2527..
2SB465	Ge-PNP	=2SB465:60V	23a$	Tos	AL102..103,2N3612,2N3614,2N2527..
2SB466	Ge-PNP	AF-Pow,40V,0,5A,12W	22a$	Fui	AD162,2SB474,2SB481
2SB467	Ge-PNP	=2SB466:60V	22a$	Fui	-
2SB468	Ge-PNP	Sw,Pow,TV-HD,220/90V,10A,32W	23a$	Hitachi	AU113,AU213,2N4324
2SB468A	Ge-PNP	=2SB468:270/90V	23a$	-	AU106,AU109,AU111,AU112,2N5325..
2SB47	Ge-PNP	AF,LN,25V,0,05A,0,08W	2a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB470	Ge-PNP	AF,25V,0,05A,0,08W	2a	Fui	AC125..126,AC151,2SB54,2SB56
2SB471	Ge-PNP	AF-Pow,60V,10A,30W	23a$	Hitachi	AL100..101,2N2289,2N2292,2N2527..
2SB472	Ge-PNP	=2SB471:80V	23a$	Hit	AL100..101,2N2289,2N2292,2N2527..
2SB473	Ge-PNP	AF-Pow,32V,1A,4,3W	22a$	Mat	AD162,2SB474,2SB481
2SB474	Ge-PNP	AF-Pow,35V,2A,12W	22a$	Sanyo	(AD162,2SB481)
2SB475	Ge-PNP	AF,20V,0,3A,0,15W	2a	Mat	AC128,AC153,AC188,2SB324,2SB415
2SB476	Ge-PNP	AF-Dr/Out,20V,2A,6W(Tc=25°)	2a$	Mat	AC153,(AC128,AC188)
2SB477	Ge-PNP	Sw,Pow,30V,30A,80W	38a$	Mit	2N2152..2159
2SB478	Ge-PNP	=2SB477:60V	38a$	Mit	2N2153..2155,2N2157..2159
2SB479	Ge-PNP	=2SB477:80V	38a$	Mit	2N2155,2N2159
2SB48	Ge-PNP	AF,15V,0,1A,0,14W,B=43	2a	Son	AC125..126,AC151,2SB54,2SB56
2SB480	Ge-PNP	=2SB477:100V	38a$	Mit	2N2155,2N2159
2SB481	Ge-PNP	AF-Pow,32V,1A,6W	22a$	Mat	AD162,2SB474
2SB482	Ge-PNP	AF,35V,0,05A,0,12W	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB483	Ge-PNP	AF,Sw-Pow,80V,15A,60W	23a$	Shi	2N1551,2N1555,2N1559,2N1652..
2SB484	Ge-PNP	=2SB483:100V	23a$	Shi	2N1552,2N1556,2N1560,2N1652..
2SB485	Ge-PNP	=2SB483:140V	23a$	Shi	-
2SB486	Ge-PNP	=2SB482:ra,25V	2a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB487	Ge-PNP	AF-Pow,30V,0,5A,5W	?22	Fui	(AD162,2SB474,2SB481)
2SB488	Ge-PNP	=2SB487:60V	?22	Fui	-
2SB49	Ge-PNP	=2SB48:B=83	2a	Son	AC125..126,AC151,2SB54,2SB56
2SB491	Ge-PNP	Sw,Pow,250V,11A,40W	-	Sanyo	-
2SB492	Ge-PNP	AF-Dr/Out,25V,2A,6W(Tc=25°)	2a$	Sanyo	AC153,(AC128,AC188)
2SB492ST	Ge-PNP	=2SB492:50V	2a$	-	-
2SB493	Ge-PNP	AF,Sw-Pow,40V,1A,9W	2a$	Mat	(AD162,2SB474,2SB481)
2SB494	Ge-PNP	AF-Dr/Out,25V,1A,0,2W,B>38	2a	Mat	AC128,AC153,AC188,2SB324,2SB415
2SB495	Ge-PNP	=2SB494:B>57	2a	Mat	AC128,AC153,AC188,2SB324,2SB415
2SB495A	Ge-PNP	=2SB495:32V	2a	-	AC128,AC153,2SB324,2SB415
2SB496	Ge-PNP	AF-Dr/Out,25V,0,25A,0,3W	2a	Hit	AC128,AC152..153,AC188,2SB475
2SB497	Ge-PNP	Min,AF,LN,20V,0,03A,0,065W	37a	Fui	(AC125..126,AC151r,ACY32,2SB173)
2SB498	Ge-PNP	AF,LN,25V,0,05A,0,1W	2a	Nec	AC125..126,AC151r,ACY32,2SB173
2SB50	Ge-PNP	=2SB48:B=131	2a	Son	AC125..126,AC151,2SB54,2SB56
2SB502	Si-PNP	AF,Sw-Pow,110V,3A,25W,1MHz	22a$	Tos	BD242C,BD244C,BD940,2SB867,..
2SB502A	Si-PNP	=2SB502:5MHz,1/4µS	22a$	-	BD242C,BD244C,BD940,2SB867,..
2SB503	Si-PNP	=2SB502:70V	22a$	Tos	BD242A,BD244A,BD938,2SB682,..
2SB503A	Si-PNP	=2SB502:80V	22a$	-	BD242B,BD244B,BD938,2SB682,..
2SB504	Si-PNP	AF,Sw,80V,2A,1W,35MHz	2a$	Nec	BCX60,BSS17..18,2N5322..5323
2SB504A	Si-PNP	=2SB504:100V	2a$	-	BCX60,BSS17,2N5322
2SB505	Si-PNP	=2SB504:15W	43a$	Nec	(BD520,BD528,BD530,BD818..)
2SB506(A)	Si-PNP	AF,Sw-Pow,150V,5A,60W,10MHz	23a$	Nec	BD246D,2SB695..696,2SB713,2SB816..
2SB507	Si-PNP	AF,Sw-Pow,60V,3A,30W,8MHz	17J$	Sanyo	BD242B,BD536,BD936,2SB1064,..
2SB508	Si-PNP	=2SB507	17j$	Sanyo	BD242A,BD536,BD936,2SB1064,..

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2SB509	Si-PNP	=2SB507: 4A, 35W	22a$	Sanyo	BD244B, BD536, 2N3740..41, 2SA1262,..
2SB51	Ge-PNP	AF, 30V, 0,2A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB510	Si-PNP	AF, Sw, 80V, 1A, 0,8W, 50MHz	2a$	Nec	BC161, BSV16..17, 2N4030..33..
2SB511(E)	Si-PNP	AF, Sw-Pow, 35V, 1,5A, 10W, 8MHz	17j$	Sanyo	BD240, BD242, BD534, TIP32A, 2SA748,..
2SB512	Si-PNP	AF, Sw-Pow, 60V, 3A, 25W, >3MHz	17j$	Mat,Mic	BD242A, BD536, BD936, 2SB1064,..
2SB512A	Si-PNP	=2SB512: 80V	17j$	-	BD242B, BD538, BD938, 2SA1288,..
2SB513(A)	Si-PNP	=2SB512(A)	17j$	Mat	→2SB512(A)
2SB514	Si-PNP	AF, Sw-Pow, 50V, 2A, 20W, 8MHz	17j$	Say,Mic	BD240, BD242, BD536, BD936, TIP32A…
2SB515	Si-PNP	=2SB514	17j$	Say,Mic	TIP32A
2SB516	Ge-PNP	AF, 20V, 0,1A, 0,15W	2a	Hit	AC125..126, AC151..152, 2SB54, 2SB56
2SB518(-1,-2)	Si-PNP	Sw, Pow, -1=70V, -2=90V, 7A, 60W, >3MHz	23a$	Sony	BD246B, BDV96, BDX96, 2SA980..982..
2SB519(-1,-2)	Si-PNP	Sw, Pow, -1=90V, -2=110V, 10A, 80W, >3MHz	23a$	Sony	BD246C, BDW22C, 2N6229..31, 2SA1141..
2SB52	Ge-PNP	AF, 30V, 0,2A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB520(-1,-2)	Si-PNP	Sw, Pow, -1=110V, -2=140V, 12A, 100W, >3MHz	23a$	Sony	BD246F, 2SA908, 2SB555, 2SB681, 2SB817..
2SB521(-1,-2)	Si-PNP	AF, Sw-Pow, -1=60V, -2=85V, 5A, 43W, 7MHz	17j$	Son	BD244B, BDS44B, BD952, 2SA1012,..
2SB522(-1,-2)	Si-PNP	=2SB521	17j$	-	→2SB521
2SB523	Si-PNP	AF, Sw-Pow, 40V, 2A, 10W, 70MHz	17j$	Mit,Mic	2N5195, 2SA748, 2SA1288
2SB524	Si-PNP	=2SB523, 60V, 1,5A	17j$	-	2N5195, 2SA748, 2SA1288
2SB525	Si-PNP	GenP, 30V, 1A, 0,8W, 100MHz	7b	Mit	BC327..328, BC636, BC638, 2SB809,..
2SB526	Si-PNP	AF, Sw-Pow, 90V, 0,8A, 10W, 70MHz	17j$	Mit,Mic	2SA913(A), 2SA985(A), 2SA1111..1112, MJE350…
2SB527	Si-PNP	=2SB526: 110V	17j$	Mit	2SA913(A), 2SA985(A), 2SA1111..1112, MJE350…
2SB528	Si-PNP	=2SA526: 130V	17j$	Mit	2SA913(A), 2SA985A, 2SA1111..1112, MJE350…
2SB529	Si-PNP	AF, Sw-Pow, 40V, 2A, 10W, 70MHz	17j$	Mit,Mic	2N5195, 2SA748, 2SA1288
2SB53	Ge-PNP	AF, 30V, 0,25A, 0,2W	2a	Son	AC128, AC152..153, AC188, 2SB324
2SB530	Si-PNP	AF, Sw-Pow, 110V, 6A, 80W	23a$	Tos	BD246C, 2SB688, 2SB776, 2SA981..982..
2SB531	Si-PNP	AF, Sw-Pow, 90V, 6A, 50W, 8MHz	23a$	Tos	BD246B, BD314, BDV94, BDW52C, BDX94..
2SB532	Si-PNP	AF, Sw-Pow, 80V, 5A, 60W, 10MHz	23a$	Mat	BD246B, BD314, BDV94, BDW52C, BDX94..
2SB533	Ge-PNP	AF, Sw, 20V, 2A, 6W(Tc=25°)	2a$	Mat	2N1038, 2N2564
2SB534	Ge-PNP	AF, 20V, 0,5A, 0,2W	2a	Hit	AC128, AC153, AC188, 2SB324, 2SB415
2SB535	Ge-PNP	AF, Sw, 35V, 1A, 0,25W, 6W(Tc=25°)	2a	Hit	2N1038, 2N2564, (AC128, AC153)
2SB536	Si-PNP	AF, Sw-Pow, 130V, 1,5A, 20W, 40MHz	17j$	Nec	2SA968(A,B), 2SA985A, 2SB628(A), MJE350…
2SB537	Si-PNP	=2SB536	17j$	Nec	TIP32C
2SB538	Ge-PNP	AF, Sw-Pow, 65V, 15A, 75W	23a$	Hit	2N1551..52, 2N1555..56, 2N1559..60
2SB539(A)	Si-PNP	AF, Sw-Pow, 130V, 10A, 100W, 8MHz	23a$	Nec	BD246D, 2SA1146, 2SB555, 2SB681..
2SB539B	Si-PNP	=2SB539(A): 150V	23a$	-	BD246D, 2SA1386(A), 2SB681, 2SB697..
2SB539C	Si-PNP	=2SB539(A): 160V	23a$	-	BD246D, 2SA1147, 2SB697, 2SB817..
2SB54	Ge-PNP	AF, 30V, 0,15A, 0,15W	2a	Tos	AC125..126, AC151, 2SB56, 2SB175
2SB540	Ge-PNP	AF, Sw, 50V, 2A, 6W(Tc=25°)	2a$	Tos	2N1039, 2N2565
2SB541	Si-PNP	AF, Sw-Pow, 110V, 8A, 80W, 9MHz	23a$	Nec	BD246C, 2SA981..982, 2SA1141, 2SB681,..
2SB542	Si-PNP	GenP, 20V, 0,5A, 0,3W, 150MHz	7b	Mit	BC327..328, BC636, 2SA1515, 2SB910,..
2SB544(MP,P1,P2)	Si-PNP	GenP, Lo-sat, 25V, 1A, 0,9W, 180MHz	7c(9mm)	Sanyo	2SA966, 2SA1382, 2SB892, 2SB927..
2SB546(A)	Si-PNP	TV-VD, 200V, 2A, 20W, 5MHz	17j$	Nec	BD240F, 2SA1133, 2SB630, 2SB861
2SB546A	Si-PNP	200V, 2A, 25W, 5MHz	-		-
2SB547(A)	Si-PNP	=2SB546(A)	17j$	Nec	→2SB546(A)
2SB548	Si-PNP	AF-Pow, 100/80V, 0,8A, 10W, 70MHz	14h$	Nec	BD140, BD231, BD238, 2SA1184, 2SA1220(A)..
2SB549	Si-PNP	=2SB548: 120/100V	14h$	Nec	2SA1178, 2SA1184, 2SA1220(A), 2SA1358, BD238
2SB55	Ge-PNP	AF, 60V, 0,15A, 0,15W	2a	Tos	ACY24, ASY48, 2N2042..43
2SB550	Si-PNP	AF, Sw-Pow, 100V, 5A, 25W, 20MHz	22a$	Nec	BD244C, BD540C, BD954, 2SB633,..
2SB551	Si-PNP	AF, Sw-Pow, 50V, 3A, 25W, 32MHz	22a$	Hit	BD242, BD536, BD936, BDX14, 2SB1064+
2SB552	Si-PNP	Sw, Pow, 220V, 15A, 150W, 3,5MHz	23a$	Toshiba	BUW96, 2SA1117, 2SA1294, 2SB613
2SB553	Si-PNP	Lo-sat, 70V, 7A, 40W, 10MHz	17j$	Tos	2SA1290, 2SB921L, TIP42C
2SB554	Si-PNP	AF-Pow, 180V, 15A, 150W, 6MHz	23a$	Toshiba	2SA908..09, 2SA1116..17, 2SA1147..
2SB555	Si-PNP	=2SB554: 140V, 12A, 100W	23a$	Tos	2SA908..909, 2SB681, 2SB697, 2SB817..
2SB556	Si-PNP	=2SB554: 120V, 12A, 100W	23a$	Tos	2SA908..909, 2SB681, 2SB697, 2SB817..
2SB557(S)	Si-PNP	=2SB554: 120V, 8A, 80..100W	23a$	Tos	BD246D, 2SA981..982, 2SB688, 2SB696..
2SB558	Si-PNP	=2SB554: 100V, 7A, 60W	23a$	Tos	BD246C, BDV96, BDW52C, BDX96, 2SA980..982..
2SB559	Si-PNP	AF, Sw-Pow, Lo-sat, 20V, 1,2A, 8W, 150MHz	14h$	Sanyo	BD136, BD227, BD238, BD376, 2SB1009..
2SB56	Ge-PNP	AF, 30V, 0,15A, 0,15W	2a	Tos	AC128, AC151..153, AC188, 2SB324
2SB560(MP)	Si-PNP	GenP, Lo-sat, 100V, 0,7A, 0,9W, 100MHz	7c(9mm)	Say,Mic	2SA965, 2SB647, 2SA1013, 2SA1275
2SB561	Si-PNP	GenP, 25V, 0,7A, 0,5W, 350MHz	7c	Hit	(BC327..328, BC636, 2SA1705,..)
2SB562	Si-PNP	=2SB561: 1A, 0,9W	7c(9mm)	Hit	(2SA966, 2SA1382, 2SB978, 2SB892,..)
2SB563	Si-PNP	AF, Sw-Pow, 80V, 3A, 25W	22a$	Nec	BD242B, BD538, BDX14, 2SA1288;..
2SB564	Si-PNP	GenP, 30V, 1A, 1W, 110MHz	9b	NEC	BC327..328, BC636, 2SB909, 2SB1116..
2SB565(A)	Si-PNP	AF, Sw-Pow, 70V, 4A, 40W, 15MHz	17j$	Hit	BD244B, BD538, BD952, 2SB633,..

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2SB566(A)	Si-PNP	=2SB565	17j$	Hit	→2SB565
2SB566(A)K	Si-PNP	=2SB565: Hi-relVeµSion, 300/3000nS	-		-
2SB567	Si-PNP	AF, Sw-Pow, 200V, 2A, 30W	17j$	Hit	BD240F, 2SA1133, 2SB630, 2SB861
2SB568	Si-PNP	=2SB567	17j$	Hit	→2SB567
2SB569	Si-PNP-Darl	AF, Sw-Pow, 40V, 4A, 40W, B=6000	14h$	Mot	BD676, BD678, BD776, 2N6034..6036..
2SB56A	Ge-PNP	=2SB56: 45V	2a	-	ACY24, ASY48, ASY76..77, 2N1189..90
2SB57	Ge-PNP	AF, 30V, 0,1A, 0,1W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB570	Si-PNP-Darl	=2SB569: 60V	14h$	Mot	BD678, BD678, BD778, 2N6035..6036..
2SB571	Si-PNP-Darl	=2SB569: 80V	14h$	Mot	BD680, BD780, 2N6036
2SB572	Si-PNP	AF, Sw-Pow, 40V, 3A, 30W	14h$	Mot	BD176, BD186, BD438, 2N5193..95..
2SB573	Si-PNP	=2SB572: 60V	14h$	Mot	BD178, BD190, BD440, 2N5194..95..
2SB574	Si-PNP	=2SB572: 80V	14h$	Mot	BD180, BD442, 2N5195
2SB575	Si-PNP	AF, Sw-Pow, 40V, 4A, 40W	14h$	Mot	BD186, BD438, 2N5193..5195
2SB576	Si-PNP	=2SB575: 60V	14h$	Mot	BD190, BD440, 2N5194..5195
2SB577	Si-PNP	=2SB575: 80V	14h$	Mot	BD442, 2N5195
2SB578	Si-PNP	AF, Sw-Pow, 70V, 10A, 90W	16h$	Mot	BD208, MJE2955T
2SB579	Si-PNP	AF, Sw-Pow, 60V, 5A, 75W	16h$	Mot	BD200, MJE2955T, 2N5974..5976
2SB57A	Ge-PNP	AF, 45V, 0,5A, 0,225W	2a	Fui	ASY76..77, 2N1189..90
2SB58	Ge-PNP	AF, 12V, 0,05A, 0,1W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB580	Si-PNP	=2SB579: 80V	16h$	Mot	2N5975..5976, MJE2955T
2SB581	Si-PNP	=2SB579: 100V	16h$	Mot	2N5976, MJE2955T
2SB582	Si-PNP-Darl	AF, Sw-Pow, 60V, 8A, 75W, B=3000	16h$	Mot	(BDV64(A..C), TIP145..147)
2SB583	Si-PNP-Darl	=2SB582: 80V	16h$	Mot	(BDV64A..C, TIP146..147)
2SB584	Si-PNP-Darl	=2SB582: 100V	16h$	Mot	(BDV64B..C, TIP147)
2SB585	Si-PNP-Darl	AF, Sw-Pow, 60V, 8A, 100W, B=3000	23a$	Mot	2N6050, BDV64(A..C), BDX84A..C, BDX86A..C..
2SB586	Si-PNP-Darl	=2SB585: 80V	23a$	-	BDV64A..C, BDX84B..C, BDX86B..C..
2SB587	Si-PNP-Darl	AF, Sw-Pow, 60V, 12A, 150W, B=3000	23a$	Mot	2N6050, BDV64(A..C), BDW84A..D, BDX88A..C..
2SB588	Si-PNP-Darl	=2SB587: 80V	23a$	Mot	BDV64A..C, BDW84B..D, BDX88B..C..
2SB589	Si-PNP-Darl	=2SB587: 100V	23a$	Mot	BDV64B..C, BDW84C..D, BDX88C..
2SB59	Ge-PNP	AF, Sw, 30V, 0,1A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB595	Si-PNP	AF-Out, 100V, 5A, 40W, 5MHz	17j$	Tos	BD244C, BD544C, BD912, BD954, 2SB633,..
2SB596	Si-PNP	AF-Pow, 80V, 4A, 30W, >3MHz	17j$	Tos	BD244B, BD538, BD952, 2SB920,..
2SB598	Si-PNP	GenP, Lo-sat, 25V, 1A, 0,5W, 180MHz	7c	Say, Mic	2SB892, 2SB926..927, 2SB1229
2SB599	Si-PNP	Sw, Pow, 200V, 2A, 30W	22a$	Nec	BD240F, 2SA1133, 2SB630, 2SB861
2SB60(A)	Ge-PNP	AF, 20V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB600	Si-PNP	AF-Pow-Sw, 200V, 10A, 200W, 14MHz	23a$	NEC	MJ15016, 2SA1116..17, 2SB613, 2SB645,..
2SB601	Si-P-Darl+Di	AF, Sw-Pow, 100V, 5A, 30W, B>2000	17j$	Nec	BD650, BD902, BDW24C, BDW64C..D..
2SB603	Si-PNP	AF, Sw, 500V, 0,5A, 0,8W	2a$	Nec	2N5096
2SB604	Si-PNP	AF, Sw-Pow, 70V, 4A, 30W, 10MHz	17j$	Mat	BD244A, BD538, BD952, 2SB920,..
2SB605	Si-PNP	GenP, 60V, 0,7A, 1W, 120MHz	9b	NEC	BC638, BC640, 2SB647, 2SB910, 2SB1116..
2SB606	Si-PNP	Sw, Vid, 250V, 0,5A, 0,8W, 200/2000nS	2a$	Fui	BFT44..45, MJ5415..16, 2N5416
2SB607	Ge-PNP	AF, Sw, 30V, 1A, 3W(Tc=25°)	2a$	Mat	AC128, AC153, AC188, 2N1038, 2N2564
2SB608(A)	Si-PNP	AF, Sw-Pow, 180V, 2A, 30W	17j$	Hit	BD240E, 2SA1133, 2SB628A, 2SB861, 2SB991
2SB609	Si-PNP	AF, Sw-Pow, 100V, 4A, 40W	22a$	Hit	BD244C, BD540C, BD954, 2SB550..
2SB61	Ge-PNP	AF, 30V, 0,05A, 0,15W	2a	Fui	AC125..126, AC151, 2SB54, 2SB56
2SB611(A)	Si-PNP	AF, Sw-Pow, 150V, 7A, 60W	23a$	Hit	BD246D, 2SB696, 2SB713, 2SB816,..
2SB612(A)	Si-PNP	AF, Sw-Pow, 180V, 12A, 100W	23a$	Hit	MJ15016, BD746F, 2SA1147, 2SB645..
2SB613	Si-PNP	Sw, Pow, 250V, 15A, 150W	23a$	Hitachi	BUW42, MJ15023, MJ15025
2SB615	Si-PNP-Darl	AF, Sw-Pow, 110V, 7A, 80W, B>1100	23a$	Mit	BDV64C, BDX62C, BDX64C, 2SA1183
2SB616(A)	Si-PNP	AF, Sw-Pow, 100V, 5A, 60W, 22MHz	19j$	Nec	2SA986, 2SB758(A), 2SB773(A)
2SB617(A)	Si-PNP	=2SB616(A): 120V, 6A, 70W, 14MHz	19j$	Nec	2SA986, 2SB758(A), 2SB773A
2SB618(A)	Si-PNP	=2SB616(A): 150V, 7A, 80W, 14MHz	19j$	Nec	-
2SB619	Ge-PNP	AF, Sw, 32V, 1,3A, 0,3W	2a	Mat	AC153, 2N1038, 2N2564, (AC128)
2SB62	Ge-PNP	AF, Sw-Pow, 60V, 0,5A, 4W	22a$	Tos	-
2SB620	Si-PNP	GenP, 25V, 0,05A, 0,25W, 100MHz	7c	Mat	BC213, BC258, BC308, BC558..
2SB621(NC)	Si-PNP	GenP, 30V, 1A, 0,75W, 200MHz	7c	Matsushita	BC327..328, BC636, BC638, 2SB809..
2SB621A	Si-PNP	=2SB621: 60V	7c	-	BC638, BC640, 2SA1705, 2SB647,..
2SB622	Si-PNP	Sw, 400V, 0,3A, 0,8W, 10MHz	2a$	Sak	2N5093..96, 2SB603
2SB624	Si-PNP	AF, 30V, 0,7A, 160MHz	35a	Nec	BCW67..68, 2SA1621
2SB624-BV1	Si-PNP	-	35	Nec	→2SB624
2SB624-BV2	Si-PNP	-	35	Nec	→2SB624
2SB624-BV3	Si-PNP	-	35	Nec	→2SB624
2SB624-BV4	Si-PNP	-	35	Nec	→2SB624
2SB624-BV5	Si-PNP	-	35	Nec	→2SB624

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2SB624R	Si-PNP	=2SB624:	3Sd	-	BCW67R..68R
2SB625	Si-PNP	AF,Sw-Pow,100V,7A,60W,7MHz	23a$	Mat	BD246C,BDV96,BDX96,2SA980..982,..
2SB626	Si-PNP	=2SB625: 120V,8A,80W,6MHz	23a$	Mat	BD246C,2SA980..982,2SA1141,..
2SB627	Ge-PNP	AF,Sw-Pow,40V,10A,13W	2a$	Mat	AD136,AUY35..36
2SB628	Si-PNP	AF,Sw-Pow,160V,1,5A,20W,40MHz	17j$	Nec	2SA913A,2SA1112,2SB608,2SB861,..
2SB628A	Si-PNP	=2SB628: 180V	17j$	-	2SA913A,2SA1112,2SB608,2SB861,..
2SB63	Ge-PNP	=2SB62: 32V	22a$	Tos	AD162,2SB474
2SB630	Si-PNP	AF,Sw-Pow,200V,2A,25W,4MHz	17j$	Nec	BD240F,2SA1133,2SB861
2SB631	Si-PNP	AF,Sw-Pow,Lo-sat,100V,1A,8W,110MHz	14h$	Sanyo	BD140,BD231,BD238,BD380,2SA1184,..
2SB631K	Si-PNP	=2SB631: 120V	14h$	-	2SA1178,2SA1184,2SA1220(A),2SA1358
2SB632	Si-PNP	AF,Sw-Pow,25V,2A,10W,100MHz	14h$	Sanyo	BD330,BD436,BD376,2SB1009,..
2SB632K	Si-PNP	=2SB632: 35V	14h$	-	BD376,2SB744(A),2SB1009,..
2SB633	Si-PNP	AF,Sw-Pow,100V,6A,40W,15MHz	17j$	Sanyo	BD244C,BD544C,BD802,TIP42C
2SB633P	Si-PNP	=2SB633: 50W	19j$	-	2SB617..618,2SB773(A),2SB758(A)
2SB634	Si-PNP	AF,Sw-Pow,120V,7A,60W,15MHz	23a$	Sanyo	BD246C,2SA1141,2SB981..982,..
2SB635	Ge-PNP	AF,32V,0,15A,0,15W	7c(9mm)	Mat	AC125..126,AC151,2SB54,2SB56
2SB636	Ge-PNP	AF,LN,32V,0,15A,0,15W	7c(9mm)	Mat	AC125..126,AC151r,ACY32,2SB173
2SB637(K)	Si-PNP	GenP,50V,0,1A,0,3W,200MHz	7c	Hitachi	BC212,BC257,BC307,BC557,..
2SB638(H)	Si-P-Darl+Di	AF,Sw-Pow,100V,10A,80W,B>1000	23a$	Hit	BDV64B,BDX84C,BDX86C,2N6052,..
2SB639(H)	Si-P-Darl+Di	=2SB638: 100W	23a$	Hit	BDV64B,BDX84C,BDX86C,2N6052,..
2SB64	Ge-PNP	AF,Sw-Pow,100V,6A,25W	23a$	Tos	AL102..103,2N3616,2N3618,2SB231
2SB640	Ge-PNP	AF,25V,0,3A,0,15W	7c(9mm)	Mat	AC128,AC152..153,AC188,2SB475
2SB641	Si-PNP	GenP,30V,0,1A,0,4W,80MHz	9c	Mat	BC213,BC258,BC308,BC558,..
2SB642	Si-PNP	=2SB641: 60V	9c	Mat	BC212,BC256,BC266,BC556,..
2SB643	Si-PNP	GenP,30V,0,5A,0,6W,200MHz	9c	Mat	BC327..328,BC636,BC638,2SA1515,..
2SB644	Si-PNP	=2SB643: 60V	9c	Mat	BC638,BC640,2N5400..01,2SA965,..
2SB645	Si-PNP	AF,Sw-Pow,200V,15A,150W,12MHz	23a$	Tos	MJ15016,2SA909,2SA1116..17,2SB613
2SB646(A)	Si-PNP	GenP,120V,0,05A,0,9W,140MHz	7c(9mm)	Hit	2SA1124,2SA1281,2SA1285(A),2SA1482
2SB647(A)	Si-PNP	GenP,120V,1A,0,9W,140MHz	7c(9mm)	Hit	2SA1013,2SA1275,2SB1212
2SB648(A)	Si-PNP	AF/Sw-Vid-Pow,180V,0,05A,140MHz	14h$	Hit	BF470,BF472,BF416,BF418,2SA1352
2SB649(A)	Si-PNP	AF/Sw-Vid-Pow,180V,1,5A,1W,140MHz	14h$	Hit	2SA1249
2SB65	Ge-PNP	AF,Sw,30V,0,1A,0,15W	2a	Fui	AC125..126,AC151,2SB54,2SB56
2SB650(H)	Si-P-Darl+Di	AF,Sw-Pow,100V,15A,100W,B>1000	23a$	Hit	BDV66A,BDW84C,BDX668,MJ4032..
2SB653(A)	Si-PNP	AF,Sw-Pow,120V,7A,60W,20MHz	23a$	Hit	BD246C,2SA1141,2SA981..982,..
2SB654(A)	Si-PNP	=2SB653(A): 80W	23a$	Hit	BD246C,2SA1141,2SA981..982,..
2SB655(A)	Si-PNP	AF,Sw-Pow,160V,12A,100W,20MHz	23a$	Hit	2SA1227A,2SA1386,2SB554,2SB697..
2SB656	Si-PNP	160V,12A,125W,20MHz	-		-
2SB656(A)	Si-PNP	=2SB655(A): 125W	23a$	Hit	MJ15016,2SA909,2SA1116..17,2SB554,..
2SB66(H)	Ge-PNP	AF,30V,0,07A,0,15W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB668	Si-PNP-Darl	AF,Sw-Pow,60V,3A,25W,B>1000	17j$	Mat	BD716,BDW24A,BDW54A,TIP32A,2SB751,..
2SB668A	Si-PNP-Darl	=2SB668: 80V	17j$	-	BD718,BDW24B,BDW54B,2SB751A,..
2SB669	Si-PNP-Darl	AF,Sw-Pow,70V,4A,40W,B>1000	17j$	Mat	BD718,BDW24B,BDW54B,BDW64B,TIP32B...
2SB669A	Si-PNP-Darl	=2SB669: 90V	17j$	-	BD902,BDW24C,BDW54C,BDW64C,..
2SB67(H)	Ge-PNP	AF,Sw,30V,0,15A,0,35W	1a	Hit	AC125..126,AC151,2SB54,2SB56
2SB670	Si-PNP-Darl	AF,Sw-Pow,90V,5A,60W,B>1000	23a$	Mat	BDV64B,BDX62B,TIP147,2SA1183,..
2SB670A	Si-PNP-Darl	=2SB670: 110V	23a$	-	BDV64C,BDX62C,TIP147,2SA1183,..
2SB671	Si-PNP-Darl	AF,Sw-Pow,100V,7A,80W,B>1000	23a$	Mat	BDV64B,BDX62B,BDX84C,TIP147,..
2SB671A	Si-PNP-Darl	=2SB671: 120V	23a$	-	BDV64C,BDW84D,BDX62C,BDX64C
2SB672	Si-PNP-Darl	AF,Sw-Pow,120V,8A,110W,B>1000	23a$	Mat	BDV64C,BDV66B,BDW84D,BDX64C
2SB672A	Si-PNP-Darl	=2SB672: 140V	23a$	-	BDV66C
2SB673	Si-P-Darl+Di	AF,Sw-Pow,100V,7A,40W,B>2000	17j$	Tos	BD650,BD902,BDW74C,BDW94C,BDX54C..
2SB674	Si-P-Darl+Di	=2SB673: 80V	17j$	Tos	BD648,BD900,BDW74B,BDW94B,BDX54B..
2SB675	Si-P-Darl+Di	=2SB673: 60V	17j$	Tos	BD646,BD898,BDW74A,BDW94B,BDX54A..
2SB676	Si-P-Darl+Di	AF,Sw-Pow,100V,4A,30W,B>2000	17j$	Tos	BD902,BDW24C,BDW54C,BDW64C,TIP127...
2SB677	Si-P-Darl+Di	=2SB676: 60V	17j$	Tos	BD898,BDW24A,BDW54A,BDW64A,TIP125...
2SB678	Si-PNP-Darl	AF,Sw,100V,1,5A,8W(Tc=25°),B>2000	2a$	Tos	(BD682)
2SB679	Si-PNP-Darl	=2SB678: 10W	17j$	Tos	2SB751B,BDW54C,TIP117
2SB67A(AH)	Ge-PNP	=2SB67: 60V	1a	-	ACY24,ASY48,ASY77,2SB55
2SB68(H)	Ge-PNP	AF,Sw,105V,0,1A,0,05W	2a	Hit	ACY39,2N2042..2043
2SB681	Si-PNP	AF,Sw-Pow,150V,12A,100W,13MHz	23a$	Tos	BD746E,MJE5852,2SA908,2SA1227A,2SB697..
2SB682	Si-PNP	AF,Sw-Pow,100V,4A,30W,8MHz	17j$	Mit	BD244C,BD540C,BD954,2SB633,..
2SB683	Si-PNP	AF,Sw-Pow,100V,5A,40W,8MHz	17j$	Mit	BD244C,BD540C,BD954,2SB633,..
2SB685	Si-PNP-Darl	AF,Sw-Pow,110V,7A,80W,30MHz,B>2000	18j$	Mit	BDV64C,BDW84D,2SA1183
2SB686	Si-PNP	AF-Out,100V,6A,60W,10MHz	18j$	Tos	BD246C,BDV96,TIP36C,2SA1141,2SB775..76,..

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2SB688	Si-PNP	AF,Sw-Pow,120V,8A,80W,10MHz	18j$	Tos	BD246C,2SA1141,2SA1146,2SA1186,..
2SB689	Si-PNP	AF,Sw-Pow,100V,4A,40W	17j$	Hit	BD244C,BD540C,BD954,2SB633,TIP42C…
2SB69	Ge-PNP	AF,Sw-Pow,60V,6A,25W	23a$	Tos	AL102..103,2N3612,2N3614,2SB231..
2SB690	Si-PNP	AF,Sw-Pow,100V,4A,40W,20MHz	17j$	Hit	BD244C,BD540C,BD954,2SB633,TIP42C…
2SB691	Si-PNP	AF,Sw-Pow,130V,5A,60W,7MHz	18j$	Mat	BD246D,2SA1146,2SB695,2SB713,2SB816..
2SB692	Si-PNP	AF,Sw-Pow,150V,6A,70W,7MHz	18j$	Mat	BD246D,2SA1294,2SA1386A,2SB695,2SB713
2SB693(H)	Si-P-Darl+Di	AF,Sw-Pow,100V,20A,125W,B>1000	23a$	Hit	BDX68B,MJ11013,2N6287
2SB694(H)	Si-P-Darl+Di	=2SB693:2SA	23a$	Hit	BDX68B,MJ11013,MJ11015
2SB695	Si-PNP	AF,Sw-Pow,170V,7A,80W,7MHz	18j$	Mat	BD246E,2SA1294,2SA1386A,2SB713
2SB696(K)	Si-PNP	AF,Sw-Pow,150V,8A,80W,15MHz	23a$	Sanyo	BD246D,2SA1186,2SB681,2SB697,..
2SB697	Si-PNP	AF,Sw-Pow,160V,12A,100W,15MHz	23a$	Sanyo	BD746F,MJE5852,2SA1147,2SB554,2SB645,..
2SB697K	Si-PNP	=2SB697:180V	23a$	-	MJ15016,BD746F,2SA1147,2SB645,..
2SB698	Si-PNP	GenP,Lo-sat,25V,0,7A,0,6W,250MHz	7c	Sanyo	2SA1703,2SB892,2SB926..927
2SB699	Si-PNP	AF,Sw-Pow,160/120V,12A,100W	20j$	Hit	2SA1076,2SA1095,2SA1166(A),2SA1215,..
2SB70	Ge-PNP	AF,30V,0,01,0,12SW,B=30	1a	Mat	AC125..126,AC151,2SB54,2SB56
2SB700	Si-PNP	160V,12A,100W	-		-
2SB700(A)	Si-PNP	=2SB699:160/140V	20j$	Hit	2SA1076,2SA1095,2SA1166(A),2SA1215,..
2SB701	Si-PNP	AF,Sw-Pow,160V,12A,120W	20j$	Hit	2SA1076,2SA1095,2SA1166(A),2SA1215,..
2SB702(A)	Si-PNP	AF,Sw-Pow,160V,12A,125W	20j$	Hit	2SA1076,2SA1095,2SA1166(A),2SA1215,..
2SB703(A)	Si-PNP	AF,Sw-Pow,100V,4A,40W,18MHz	17j$	Nec	BD244C,BD540C,BD954,2SB682,..
2SB705	Si-PNP	AF,Sw-Pow,140V,10A,120W,17MHz	20j$	Nec	2SA1094..1095,2SA1187,2SB755,..
2SB705A	Si-PNP	=2SB705:150V	20j$	-	2SA1076,2SA1095,2SA1187,2SB755..
2SB705B	Si-PNP	=2SB705:160V	20j$	-	2SA1076,2SA1095,2SA1166(A),2SA1215,..
2SB706	Si-PNP	AF,Sw-Pow,180V,10A,200W,14MHz	4-SILP	Nec	2N6107
2SB706A	Si-PNP	=2SB706:220V	4-SILP	-	-
2SB707	Si-PNP	AF,Sw-Pow,80V,7A,40W	17j$	Nec	2N6107,BD244B,BD544B,BD800,BD810,..
2SB708	Si-PNP	AF,Sw-Pow,80V,7A,40W	17j$	Nec	2N6107,BD244B,BD544B,BD800,BD810,..
2SB709	Si-PNP	GenP,25V,0,1A,80MHz	35a	Matsushita	BC856..858,BCW29..30,BCW69..70,..
2SB709A	Si-PNP	=2SB709:45V	35a	-	BC856..857,BCW69..70,BCW89..
2SB709A-Q	Si-PNP	-	35	Mat	→2SB709A
2SB709A-R	Si-PNP	-	35	Mat	→2SB709A
2SB709A-S	Si-PNP	-	35	Mat	→2SB709A
2SB709-Q	Si-PNP	-	35	Mat	→2SB709
2SB709-R	Si-PNP	-	35	Mat	→2SB709
2SB709-S	Si-PNP	-	35	Mat	→2SB709
2SB71	Ge-PNP	=2SB70:a=50	1a	Mat	AC125..126,AC151,2SB54,2SB56
2SB710	Si-PNP	GenP,30V,0,5A,200MHz	35a	Matsushita	BC807..808,BCW67..68,BCX17..18,..
2SB710A	Si-PNP	-	35	Mat	→2SB710A
2SB710A-Q	Si-PNP	-	35	Mat	→2SB710A
2SB710A-R	Si-PNP	-	35	Mat	→2SB710A
2SB710A-S	Si-PNP	-	35	Mat	→2SB710A
2SB710-Q	Si-PNP	-	35	Mat	→2SB710
2SB710-R	Si-PNP	-	35	Mat	→2SB710
2SB710-S	Si-PNP	-	35	Mat	→2SB710
2SB711	Si-PNP-Darl	AF,Sw-Pow,80V,6A,50W,B=1000	17j$	Sak	BD648,BD900,BDW24B,BDW74B,..
2SB712	Si-PNP-Darl	=2SB711:100V	17j$	Sak	BD650,BD902,BDW24C,BDW74C,TIP107…
2SB713	Si-PNP	AF,Sw-Pow,200V,9A,100W,7MHz	18j$	Mat	BD246F,MJE5852,2SA1294
2SB714	Ge-PNP	AF,Sw,20V,2A,6W(Tc=25°)	2a$	Mat	AC153,2N1038,2N2564
2SB715	Si-PNP	GenP,100V,0,05A,0,75W,150MHz	7c(9mm)	Hit	2SA1124,2SA1281,2SA1285(A),2SA1482
2SB716	Si-PNP	=2SB715,120V	7c(9mm)	Hit	2SA1124,2SA1281,2SA1285(A),2SA1482
2SB716A	Si-PNP	=2SB715,140V	7c(9mm)	-	2SA1124,2SA1281,2SA1285A,2SA1482
2SB717	Si-PNP	AF/Sw-Vid-Pow,160V,0,05A,140MHz	17j$	Hit	2SA1383,MJE5852
2SB718	Si-PNP	=2SB717:200V	17j$	Hit	MJE5852
2SB719	Si-PNP	AF,Sw-Pow,160V,2A,25W,100MHz	17j$	Hit	2SA1079,2SA1133
2SB720	Si-PNP	=2SB719:200V	17j$	Hit	2SA1133
2SB721	Si-PNP	GenP,25V,0,7A,0,625W,350MHz	7e	Hit	(BC327..328,BC636,2SB909..910,..)
2SB722	Si-PNP	AF,Sw-Pow,160V,15A,150W	23a$	Hit	MJ15016,MJE5852,2N6609,2SA1116..17,2SB554,..
2SB723	Si-PNP	=2SB722:200V	23a$	Hit	MJ15016,2SA909,2SA1116..17,2SB645,..
2SB724	Si-PNP	AF,Sw-Pow,60V,3A,25W	17j$	Mat	BD242A,BD536,BD936,TIP32A,2SB1064,..
2SB725	Si-PNP	GenP,60V,0,1A,0,45W,80MHz	7c	Mat	BC212,BC256,BC266,BC556,..
2SB726	Si-PNP	GenP,80V,0,1A,0,25W,150MHz	7c	Mat	BC556,2SA970,2SA1136..1137,2SA1285..
2SB727(K)	Si-P-Darl+Di	AF,Sw-Pow,120V,6A,50W,B>1000	17j$	Hit	BD652,BDT20,BDW64D,BDW74D,..
2SB73	Ge-PNP	AF,LN,10V,2mA,0,02W	2a	Hit	AC125..126,AC151r,ACY32,2SB173
2SB731	Si-PNP	AF,Sw-Pow,Lo-sat,60V,1A,10W,75MHz	14h$	Nec	BD138,BD229,BD378,2SB874..875,..

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2SB733	Si-PNP	AF,Lo-sat,20V,2A,1W,>50MHz	9b	NEC	2SA1704,2SB892,2SB926..927,2SB1433
2SB734	Si-PNP	GenP,60V,1A,1W,80MHz	9b	NEC	2SA1315,2SA1429,2SB1116,2SB1229..
2SB736	Si-PNP	GenP,60V,0,3A,100MHz	35a	NEC	BCW68,2SA1366,2SB1198
2SB736A	Si-PNP	=2SB736:80V	35a	-	BCX42,2SB1198
2SB736A-BS1	Si-NPN	-	35	Nec	→2SB736A
2SB736A-BS2	Si-NPN	-	35	Nec	→2SB736A
2SB736A-BS3	Si-NPN	-	35	Nec	→2SB736A
2SB736A-BS4	Si-NPN	-	35	Nec	→2SB736A
2SB736A-BS5	Si-NPN	-	35	Nec	→2SB736A
2SB736AR	Si-PNP	=2SB736:80V	35d	-	BCX42R
2SB736-BW1	Si-PNP	-	35	Nec	→2SB736
2SB736-BW2	Si-PNP	-	35	Nec	→2SB736
2SB736-BW3	Si-PNP	-	35	Nec	→2SB736
2SB736-BW4	Si-PNP	-	35	Nec	→2SB736
2SB736-BW5	Si-PNP	-	35	Nec	→2SB736
2SB736R	Si-PNP	=2SB736:	35d	-	BCW68R
2SB737	Si-PNP	AF,LN,50V,0,3A,0,25W,100MHz	7c	Rhm	BC416,BC560,2SA970,2SA1136..1137,..
2SB738	Si-PNP	AF-Pow,20/16V,2A,0,9W,150MHz	7c(9mm)	Hit	2SA1382,2SB892,2SB927,2SB1312
2SB739	Si-PNP	=2SB738:20/20V	7c(9mm)	Hit	2SA1382,2SB892,2SB927,2SB1312
2SB73N	Ge-PNP	=2SB73:18V,40mA,0,065W	2a	-	AC125..126,AC151r,ACY32,2SB173
2SB74	Ge-PNP	AF,16V,15mA,0,08W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB740	Si-PNP	AF-Pow,70/50V,1A,0,9W	7c(9mm)	Hit	2SA1013,2SA1315,2SB647,2SB1212
2SB741	Si-PNP	=2SB740:70/70V	7c(9mm)	Hit	2SA1013,2SA1315,2SB647,2SB1212
2SB742	Si-PNP	AF,Sw-Pow,20V,2A,10W	14h$	Nec	BD176,BD234,BD330,BD376,..
2SB743	Si-PNP	AF,Sw-Pow,40V,3A,10W,55MHz	14h$	Nec	BD786,MJE172,MJE250..254,2SB986
2SB744(A)	Si-PNP	AF,Sw-Pow,70V,3A,10W,45MHz	14h$	Nec	BD788,BD790,MJE250..254
2SB745	Si-PNP	GenP,LN,35V,0,05A,0,4W,150MHz	9c	Mat	BC214,BC259,BC309,BC559,2SA1137+
2SB745A	Si-PNP	=2SB745:55V	9c	-	BC416,BC560,2SA970,2SA1136..1137,..
2SB746	Si-PNP	GenP,25V,0,5A,0,4W,260MHz	7c	Hit	BC327..328,BC636,BC638,2SB909,..
2SB747	Si-PNP	AF,Sw-Pow,80V,5A,55W,7MHz	17j$	Mat	BD244B,BD544B,BD952,2SB920L,..
2SB748(A)	Si-PNP	AF,Sw-Pow,120V,6A,60W,20MHz	20j$	Hit	2SA1075..1076,2SA1094,2SB705(A,B),..
2SB749(A)	Si-PNP	AF,Sw-Pow,120V,7A,80W,20MHz	20j$	Hit	2SA1075..1076,2SA1094,2SB705(A,B),..
2SB75(H)	Ge-PNP	AF,25V,0,1A,0,15W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB750	Si-P-Darl+Di	AF,Sw-Pow,60V,2A,35W,B>1000	17j$	Mat	BD716,BDW24A,BDW54A,BDW64A,TIP115...
2SB750A	Si-P-Darl+Di	=2SB750:80V	17j$	-	BD718,BDW24B,BDW54B,BDW64B..
2SB750B	Si-P-Darl+Di	=2SB750:100V	17j$	-	BDW24C,BDW54C,BDW64C
2SB751	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,40W,B>1000	17j$	Mat	BD646,BD898,BDW24A,BDW64A,BDX54B...
2SB751A	Si-P-Darl+Di	=2SB751:80V	17j$	-	BD648,BD900,BDW24B,BDW64B..
2SB751B	Si-P-Darl+Di	=2SB751:100V	17j$	-	BD650,BD902,BDW24C,BDW64C..
2SB753	Si-PNP	Lo-sat,100V,7A,40W,10MHz	17j$	Tos	2SA1293,BD912
2SB754	Si-PNP	AF,Sw-Pow,Lo-sat,50V,7A,60W,10MHz	18j$	Tos	2SB827,TIP36B
2SB755	Si-PNP	AF,Sw-Pow,150V,12A,120W,20MHz	20j$	Tos	2SA1076,2SA1166(A),2SA1187,2SA1095,..
2SB756	Si-PNP	AF,Sw-Pow,200V,15A,150W,20MHz	20j$	Tos	2SA1169..1170,2SA1295,2SA1333
2SB757	Si-PNP	AF,Sw-Pow,40V,15A,80W	18j$	Fjd	BD250,BD546,BD746,2SA1292
2SB758	Si-PNP	AF,Sw-Pow,120V,7A,80W	19j$	Nec	2SA986,2SB618
2SB758A	Si-PNP	=2SB758:130V	19j$	-	2SA986,2SB618
2SB759	Si-PNP	GenP,25V,0,05A,0,25W,200MHz	40c	Mat	BC213,BC258,BC308,BC558..
2SB759A	Si-PNP	=2SB759:45V	40c	-	BC212,BC257,BC307,BC557..
2SB75A(AH)	Ge-PNP	=2SB75:45V	2a	-	ACY24,ASY48,2SB55
2SB76	Ge-PNP	AF,12V,0,07A,0,15W	2a	Hit	AC125..126,AC151,2SB54,2SB56
2SB760	Si-PNP	AF,Sw-Pow,60V,1A,30W	17j$	Mat	BD240A,BD242A,2SA748,2SA1288..
2SB760A	Si-PNP	=2SB760:80V	17j$	-	BD240B,BD242B,2SA985(A),2SA1288..
2SB760B	Si-PNP	=2SB760:100V	17j$	-	BD240C,BD242C,2SA985(A),2SA1393..
2SB761	Si-PNP	AF,Sw-Pow,60V,3A,35W	17j$	Mat	BD242A,BD536,BD936,2SA1262..
2SB761A	Si-PNP	=2SB761:80V	17j$	-	BD242B,BD538,BD938,2SB682..
2SB761B	Si-PNP	=2SB761:100V	17j$	-	BD242C,BD938,2SB633,2SB682..
2SB762	Si-PNP	AF,Sw-Pow,60V,4A,40W	17j$	Mat	BD244A,BD536,BD950,2SA1262..
2SB762A	Si-PNP	=2SB762:80V	17j$	-	BD244B,BD538,BD952,2SB920L..
2SB762B	Si-PNP	=2SB762:100V	17j$	-	BD244C,BD540C,BD954,2SB633..
2SB763	Si-PNP	AF,Sw-Pow,60V,5A,60W	18j$	Mat	BD246A,BDV92,2SB775,2SB688..
2SB763A	Si-PNP	=2SB763:80V	18j$	-	BD246B,BDV94,2SB775,2SB688..
2SB763B	Si-PNP	=2SB763:100V	18j$	-	BD246C,BDV96,2SB775,2SB688..
2SB764	Si-PNP	GenP,60V,1A,0,9W,150MHz	7c(9mm)	Sanyo	2SA1315,2SB647,2SB892,2SB1041..
2SB765(K)	Si-P-Darl+Di	AF,Sw-Pow,120V,3A,30W,B>1000	17j$	Hit	BDT20,BDW54D,BDW64D

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2SB766	Si-PNP	GenP, 30V, 1A, 200MHz	39b	Mat	BC869, BCX69, 2SA1203, 2SA1314
2SB766A	Si-PNP	-	39	Mat	→2SB766A
2SB766A-Q	Si-PNP	-	39	Mat	→2SB766A
2SB766A-R	Si-PNP	-	39	Mat	→2SB766A
2SB766A-S	Si-PNP	-	39	Mat	→2SB766A
2SB766-Q	Si-PNP	-	39	Mat	→2SB766
2SB766-R	Si-PNP	-	39	Mat	→2SB766
2SB766-S	Si-PNP	-	39	Mat	→2SB766
2SB767	Si-PNP	GenP, 80V, 0,5A, 120MHz	39b	Mat	2SA1368, 2SB789(A), 2SB805..806
2SB767-P	Si-PNP	-	39	Mat	→2SB767
2SB767-Q	Si-PNP	-	39	Mat	→2SB767
2SB767-R	Si-PNP	-	39	Mat	→2SB767
2SB767-S	Si-PNP	-	39	Mat	→2SB767
2SB768	Si-PNP	Vid-Out, 200V, 2A, 20W, 10MHz	30j$	Nec	(2SB928(A), 2SB630, 2SB861)
2SB77(H,N)	Ge-PNP	AF, 25V, 0,1A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB772	Si-PNP	AF, Sw-Pow, Lo-sat, 40V, 3A, 10W, 80MHz	14h$	Nec	BD786, MJE172, MJE250..254, 2SB744(A)
2SB773	Si-PNP	AF, Sw-Pow, 100V, 6A, 70W	19j$	Nec	2SA986, 2SB617, 2SB618, 2SB758(A)
2SB773A	Si-PNP	=2SB773: 120V	19j$	-	2SA986, 2SB617, 2SB618, 2SB758(A)
2SB774	Si-PNP	Hi-Ueb, 30V, 0, 1A, 0, 4W, 150MHz	7c	Mat	2SB894, 2SB1206, (BC308, BC558)
2SB775	Si-PNP	AF, Sw-Pow, 100V, 6A, 60W, 18MHz	18j$	Sanyo	BD246C, BDV96, 2SA1141, 2SB688..
2SB776	Si-PNP	AF, Sw-Pow, 120V, 7A, 70W, 15MHz	18j$	Sanyo	BD246C, 2SA1146, 2SA1186, 2SB688..
2SB777	Si-PNP	AF, Sw-Pow, 80V, 10A, 80W, <1/3µS	18j$	Fjd	BD246B, BDV94, 2SA1141, 2SA1146..
2SB778	Si-PNP	=2SB777: 120V	18j$	Fjd	BD246C, 2SA1141, 2SA1146, 2SB817..
2SB779	Si-PNP	Lo-sat, 25V, 0,5A, 150MHz	35a	Mat	2SA1298, (BC807..808, BCX17..18)
2SB779-Q	Si-PNP	-	35	Mat	→2SB779
2SB779-R	Si-PNP	-	35	Mat	→2SB779
2SB779-S	Si-PNP	-	35	Mat	→2SB779
2SB77A(AH,AN)	Ge-PNP	=2SB77: 45V	2a	-	ACY24, ASY48, 2SB55
2SB78	Ge-PNP	AF, 12V, 0,07A, 0,15W	2a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB780	Si-PNP	GenP, 30V, 0,5A, 0,4W, 200MHz	40c	Mat	BC327..328, BC636, BC638, 2SB909..
2SB781	Si-PNP	AF, Sw-Pow, 50V, 4A, 30W	17j$	Hit	BD244, BD536, BD950, 2SA1262..
2SB782	Si-PNP	=2SB781: 60V	17j$	Hit	BD244A, BD536, BD950, 2SA1262..
2SB783	Si-PNP	=2SB781: 80V	17j$	Hit	BD244B, BD538, BD952, 2SB920L..
2SB786	Si-PNP-Darl	AF, Sw-Pow, 40V, 2A, 5W, 150MHz, B=10000	14h$	Rhm	2SB794..795, 2SB1008, 2SB1310
2SB787	Si-PNP	GenP, 120V, 0,05A, 0,625W	7e	Hit	2SA872A, 2SA970, 2SA1285(A), 2SB716(A)..
2SB788	Si-PNP	GenP, LN, 120V, 0,02A, 0,4W, 150MHz	9c	Mat	2SA872A, 2SA970, 2SA1038, 2SA1136..
2SB789	Si-PNP	100V, 0,5A, 1W, 120MHz	39b	Mat	BCX53, 2SA1201, 2SA1368, 2SB804..806
2SB789A	Si-PNP	-	39	Mat	→2SB789A
2SB789A-P	Si-PNP	-	39	Mat	→2SB789A
2SB789A-Q	Si-PNP	-	39	Mat	→2SB789A
2SB789A-R	Si-PNP	-	39	Mat	→2SB789A
2SB789A-S	Si-PNP	-	39	Mat	→2SB789A
2SB789-P	Si-PNP	-	39	Mat	→2SB789
2SB789-Q	Si-PNP	-	39	Mat	→2SB789
2SB789-R	Si-PNP	-	39	Mat	→2SB789
2SB789-S	Si-PNP	-	39	Mat	→2SB789
2SB79	Ge-PNP	AF, 25V, 0,15A, 0,25W	1a	Hit	AC125..126, AC151, 2SB54, 2SB56
2SB790	Si-PNP	AF, Lo-sat, 25V, 0,5A, 0,6W, 150MHz	9c	Mat	2SB892, 2SB926..927, (BC327..328)
2SB791(K)	Si-P-Darl+Di	AF, Sw-Pow, 120V, 8A, 40W, B>1000	17j$	Hit	BD652, BDT20, BDW74D, BDX54D
2SB792	Si-PNP	GenP, LN, 150V, 0,05A, 200MHz	35a	Matsushita	-
2SB792A	Si-PNP	-	35	Mat	→2SB792A
2SB792AR	Si-PNP	-	35	Mat	→2SB792A
2SB792AS	Si-PNP	-	35	Mat	→2SB792A
2SB792-Q	Si-PNP	-	35	Mat	→2SB792
2SB792-R	Si-PNP	-	35	Mat	→2SB792
2SB792-S	Si-PNP	-	35	Mat	→2SB792
2SB792-T	Si-PNP	-	35	Mat	→2SB792
2SB793	Si-PNP	AF-Dr/Out, 30V, 1A, 1W, 200MHz	9c	Mat	BC327..328, BC636, BC638, 2SB909..
2SB793A	Si-PNP	=2SB793: 60V	9c	-	BC327A, BC636, BC638, 2SB1116..
2SB794	Si-P-Darl+Di	AF, Sw-Pow, 60V, ±1,5A, 10W, B=2k..30k	14h$	Nec	BD678, BD778, 2N6035..6036
2SB795	Si-P-Darl+Di	=2SB794: 80V	14h$	Nec	BD680, BD780, 2N6036
2SB796	Si-PNP	AF, Sw-Pow, 200V, 10A, 200W, 14MHz	23a$	Nec	MJ15016, 2SA909, 2SA1116..17, 2SB723
2SB798	Si-PNP	GenP, 30V, 1A, 110MHz	39b	Nec	BC869, BCX51, BCX69, 2SA1203..
2SB798-DK	Si-PNP	-	39	Nec	→2SB798

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2SB798-DL	Si-PNP	-	39	Nec	→2SB798
2SB798-DM	Si-PNP	-	39	Nec	→2SB798
2SB799	Si-PNP	GenP,60V,0,7A,120MHz	39b	Nec	BCX53,2SA1201,2SB804..806,2SB1025
2SB799-MK	Si-PNP	-	39	Nec	→2SB799
2SB799-ML	Si-PNP	-	39	Nec	→2SB799
2SB799-MM	Si-PNP	-	39	Nec	→2SB799
2SB80(H)	Ge-PNP	AF,Sw-Pow,25V,1A,4W	22a$	Hit	AD162,2SB474
2SB800	Si-PNP	GenP,80V,0,3A,100MHz	39b	Nec	2SA1202,2SA1368,2SB767,2SB789(A)
2SB800-FK	Si-PNP	-	39	Nec	→2SB800
2SB800-FL	Si-PNP	-	39	Nec	→2SB800
2SB800-FM	Si-PNP	-	39	Nec	→2SB800
2SB801	Si-PNP	GenP,45V,1A,80MHz	39b	Nec	BCX51..53,2SA1364,2SB766A,2SB1025,..
2SB802	Si-PNP	=2SB801:60V	39b	Nec	BCX52..53,2SA1364,2SB766A,2SB1025,..
2SB803	Si-PNP	=2SB801:100V	39b	Nec	BCX53,2SB804,2SB1025
2SB804	Si-PNP	GenP,100V,1A,80MHz	39b	Nec	BCX53,2SB803,2SB1025
2SB804-AU	Si-PNP	-	39	Nec	→2SB804
2SB804-AV	Si-PNP	-	39	Nec	→2SB804
2SB804-AW	Si-PNP	-	39	Nec	→2SB804
2SB805	Si-PNP	GenP,100V,0,7A,75MHz	39b	Nec	BCX53,2SA1201,2SB803..804,2SB1025
2SB805-KK	Si-PNP	-	39	Nec	→2SB805
2SB805-KL	Si-PNP	-	39	Nec	→2SB805
2SB805-KM	Si-PNP	-	39	Nec	→2SB805
2SB806	Si-PNP	=2SB805:120V	39b	Nec	2SA1201,2SB806,2SB1025
2SB806-KP	Si-PNP	-	39	Nec	→2SB806
2SB806-KQ	Si-PNP	-	39	Nec	→2SB806
2SB806-KR	Si-PNP	-	39	Nec	→2SB806
2SB807	Si-PNP	AF,LN,150V,0,1A,200MHz	39b	Mat	-
2SB808	Si-PNP	Lo-sat,20V,0,7A,0,25W,250MHz	40c	Sanyo	2SA1705,2SB1116,(BC327..328,BC636+)
2SB81(H)	Ge-PNP	AF,Sw-Pow,80V,0,5A,2W	22a$	Hit	-
2SB810	Si-PNP	GenP,Lo-sat,30V,0,7A,0,35W,160MHz	40c	Nec	2SA1703,2SB892,2SB926..927,2SB1433
2SB811	Si-PNP	GenP,30V,1A,0,35W,110MHz	40c	Nec	BC327..328,BC636,2SB909,2SB1116..
2SB812	Si-PNP	AF,Sw-Pow,60V,4A,60W	18j$	Mat	BD246A,BDV92,2SA1141,2SB775..776,..
2SB812A	Si-PNP	=2SB812:80V	18j$	-	BD246B,BDV94,2SA1141,2SB775..776,..
2SB813	Si-PNP	AF,Sw-Pow,60V,4A,40W,20MHz	17j$	Sanyo	BD244A,BD536,BD950,2SA1262..
2SB813K	Si-PNP	=2SB813:100V	17j$	Sanyo	BD244C,BD954,2SB633,2SB682..
2SB814	Si-PNP	LN,120V,0,02A	35a	Mat	2SA1312,2SB792
2SB815	Si-PNP	=2SB808:SMD	35a	Sanyo	2SA1298
2SB815-6	Si-PNP	-	35	Sanyo	→2SB815
2SB815-7	Si-PNP	-	35	Sanyo	→2SB815
2SB816	Si-PNP	AF,Sw-Pow,150V,8A,80W,15MHz	18j$	Sanyo	BD246D,2SA1186,2SA1227A,2SB713
2SB817	Si-PNP	AF,Sw-Pow,160V,12A,100W,15MHz	18j$	Sanyo	BD746F,2SA1294,2SA1386(A)
2SB818(K)	Si-P-Darl+Di	AF,Sw-Pow,100V,10A,80W,B>1000	20j$	Hit	2SB853
2SB819	Si-PNP	AF-Dr/Out,50V,1,5A,1W,150MHz	9c	Mat	MPS750..751,2SA1315,2SA1382,2SB892..
2SB82(H)	Ge-PNP	=2SB81:100V	22a$	Hit	-
2SB820	Si-PNP	AF,Sw-Pow,350V,1A,15W	30j$	Nec	2SA1412,(2SA1009(A),2SA1236,2SA1397)
2SB821	Si-PNP	=2SB737:	9c	Rhm	→2SB737
2SB822	Si-PNP	AF-Dr/Out,40V,2A,0,75W,100MHz	9c	Rhm	MPS750,2SA1315,2SA1382,2SB911..
2SB823	Si-PNP	AF,Sw-Pow,100V,6A,40W	17j$	Sanyo	BD244C,BD544C,BD802,2SB633..
2SB824	Si-PNP	Sw,Pow,Lo-sat,60V,5A,30W,30MHz	17j$	Sanyo	2SA1012,2SA1289,2SB920L
2SB825	Si-PNP	Sw,Pow,Lo-sat,60V,7A,40W,10MHz	17j$	Sanyo	2SA1290,2SB919,2SB921L
2SB826	Si-PNP	Sw,Pow,Lo-sat,60V,12A,40W,10MHz	17j$	Sanyo	2SA1328,2SB903
2SB827	Si-PNP	Sw,Pow,Lo-sat,60V,7A,60W,10MHz	18j$	Sanyo	2SA1292,2SB922L
2SB828	Si-PNP	Sw,Pow,Lo-sat,60V,12A,80W,10MHz	18j$	Sanyo	2SA1292,2SB922L
2SB829	Si-PNP	Sw,Pow,Lo-sat,60V,15A,90W,20MHz	18j$	Sanyo	2SB1230
2SB83(H)	Ge-PNP	AF,Sw-Pow,40V,3A,44W	23a$	Hit	AD149,2N2138,2N2143,2SB449..
2SB830	Si-PNP	AF-Dr/Out,20V,2A,0,9W	7c(9mm)	Hit	2SA1382,2SB738..739,2SB892,2SB1312,..
2SB831	Si-PNP	GenP,25V,0,7A,65MHz	35a	Hitachi	BCW67..68,2SA1298,2SA1621
2SB831-B	Si-PNP	-	35	Hit	→2SB831
2SB831-C	Si-PNP	-	35	Hit	→2SB831
2SB832	Si-PNP	Sw,Pow,TV-HD,1000V,10mA,25W,4,5MHz	17j$	Son	-
2SB833	Si-P-Darl+Di	Sw,Pow,80V,30A,150W,B=4000	23a$	Tos	BDX68A..C,MJ11013,MJ11015,2SB694
2SB835	Si-PNP	AF-Dr/Out,20V,1A,0,1W,200MHz	9c	Mat	BC327..328,BC636,BC638,2SB909..
2SB836	Si-PNP	AF,Sw-Pow,25V,2,5A,20W	30j$	Hit	2SA1243,2SB906,2SB962,2SB1184..
2SB836L	Si-PNP	=2SB836:	14h$	-	BD330,2SB744(A)

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2SB837	Si-PNP	=2SB836:35V	30j$	Hit	2SA1243,2SB906,2SB962,2SB1184..
2SB837L	Si-PNP	=2SB837:	14h$	-	BD330,2SB744(A)
2SB838	Si-PNP	AF,Sw-Pow,50V,2A,20W,130MHz	30j$	Hit	2SA1241,2SB839,2SB957..958,2SB1201,..
2SB838L	Si-PNP	=2SB838:	14h$	-	BD376,2SB744(A),2SB874..875..
2SB839	Si-PNP	=2SB838:80V	30j$	Hit	2SA1S93,2SB957..958,2SB1215..16..
2SB839L	Si-PNP	=2SB839:	14h$	-	BD378,2SB874..875
2SB84(N)	Ge-PNP	=2SB83:60V	23a$	Hit	AD166..167,2N2139,2N2144..
2SB840	Si-PNP	AF,Sw-Pow,180/120V,1,5A,20W,140MHz	30j$	Hit	2SA1552,2SB768
2SB840L	Si-PNP	=2SB840:	14h$	-	2SA1249,2SB649
2SB841	Si-PNP	=2SB840:180/160V	30j$	Hit	2SA1552,2SB768
2SB841L	Si-PNP	=2SB841:	14h$	-	2SA1249,2SB649
2SB842	Si-PNP	=2SB840:200V	30j$	Hit	2SB768,(2SB928(A),2SA968B,2SA1133,..)
2SB842L	Si-PNP	=2SB841:	14h$	-	-
2SB843	Si-PNP	AF,Sw-Pow,50V,5A,10W	14h$	Hit	2SB1151
2SB844	Si-PNP	AF,Sw-Pow,120V,1A,10W,B=160	30j$	Hit	2SA1592,2SA1225,2SB959..960,2SB905,..
2SB845	Si-PNP	=2SB944:B=100	30j$	Hit	2SA1592,2SA1225,2SB959..960,2SB905,..
2SB846	Si-PNP	AF,Sw-Pow,25V,1A,10W	30j$	Hit	2SA1241,2SB838,2SB1182,(2SA748,..)
2SB848	Si-PNP	AF,Sw-Pow,100V,6A,70W	16j$	Nec	BD246C,BDV96,2SA1141,2SA1186..
2SB849	Si-PNP	AF,Sw-Pow,120V,7A,80W,14MHz	16j$	Nec	BD246C,2SA1141,2SA1146,2SA1186..
2SB849A	Si-PNP	=2SB849:130V	16j$	-	BD246D,2SA1186,2SB816,2SB695..
2SB85	Ge-PNP	AF,Sw-Pow,40V,10A,50W	23a$	Hit	AL100..101,2N2288,2N2291..
2SB850	Si-PNP	AF,Sw-Pow,40V,10A,50W	17j$	Fjd	BD706,BD806,BD906
2SB850A	Si-PNP	=2SB850:80V	17j$	-	BD710,BD810,BD910
2SB851	Si-PNP	AF-Driver,80V,0,7A,0,75W,100MHz	9c	Rhm	BC640,2SA965,2SB647,2SB910..
2SB852	Si-PNP-Darl	40V,0,3A,200MHz,B>1000	?35d	Rhm	-
2SB852K	Si-PNP-Darl	=2SB852:	35a	-	BCV26,BCV46
2SB852K-A	Si-PNP-Digital	-	35	Rhm	→2SB852K
2SB852K-B	Si-PNP-Digital	-	35	Rhm	→2SB852K
2SB852-UA	Si-PNP	-	?35	Rhm	→2SB852
2SB852-UB	Si-PNP	-	?35	Rhm	→2SB852
2SB853	Si-PNP-Darl	AF,Sw-Pow,100V,15A,100W,B>1000	20j$	Hit	-
2SB854	Si-PNP-Darl	=2SB853:20A,125W	20j$	Hit	-
2SB855	Si-PNP	AF,Sw-Pow,50V,2A,20W,35MHz	17j$	Hit	BD240A,BD242A,TIP32A,2SA748,2SA1288..
2SB856	Si-PNP	=2SB855:3A	17j$	Hit	BD242A,TIP32A,2SA748,2SA1012,2SA1288..
2SB857	Si-PNP	AF,Sw-Pow,70/50V,4A,40W,15MHz	17j$	Hit	BD244A,BD536,BD950,2SB690..
2SB858	Si-PNP	=2SB857:70/60V	17j$	Hit	BD244A,BD538,BD952,2SB690..
2SB859	Si-PNP	AF,Sw-Pow,100V,4A,40W,20MHz	17j$	Hit	BD244C,BD540C,BD954,2SB682..
2SB86	Ge-PNP	=2SB85:60V	23a$	Hit	AL100..101,2N2289,2N2292..
2SB860	Si-PNP	AF,Sw-Pow,100V,4A,40W	17j$	Hit	BD244C,BD540C,BD954,2SB682..
2SB861	Si-PNP	AF,Sw-Pow,200/150V,2A,30W	17j$	Hit	BD240F,2SA1133,2SB630,2SB720
2SB862	Si-PNP-Darl	AF,Sw-Pow,120V,5A,30W,68MHz,B=5000	17j$	Fjd	BD652,BDT20,BDW64D,BDX54D
2SB863	Si-PNP	AF-Out,140V,10A,100W,15MHz	18j$	Tos	BD246D,2SA1186,2SA1227A,2SB817
2SB864	Si-PNP	GenP,55V,0,1A,0,3W	7c	Hit	BC212,BC257,BC307,BC557..
2SB865	Si-PNP-Darl	GenP,80V,1,5A,0,9W,B>4000	7c(9mm)	Sanyo	BC878,BSR61..62,2SB1129,2SB1406
2SB867	Si-PNP	AF,Sw-Pow,Lo-sat,130V,3A,30W,30MHz	17j$	Mat	2SA1644
2SB868	Si-PNP	=2SB867:4A,35W	17j$	Mat	2SA1644
2SB869	Si-PNP	=2SB867:5A,40W	17j$	Mat	2SA1644
2SB87	Ge-PNP	=2SB85:80V	23a$	Hit	AL100..101,2N2289,2N2292..
2SB870	Si-PNP	=2SB867:7A,40W	17j$	Mat	-
2SB871	Si-PNP	AF,Sw-Pow,Lo-sat,40V,10A,40W,100MHz	17j$	Mat	2SA1291,2SA1328..29,2SB903
2SB871A	Si-PNP	=2SB870:50V	17j$	-	2SA1291,2SA1328..29,2SB903
2SB872	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,45W,B>1000	17j$	Mat	BD646,BD898,BDW74A,BDX54A..
2SB872A	Si-P-Darl+Di	=2SB871:80V	17j$	-	BD648,BD900,BDW74B,BDX54B..
2SB873	Si-PNP	DC-DC Conv.,Out,30V,5A,1W,120MHz	7c(9mm)	Mat	2SB1288,2SB1306
2SB874	Si-PNP	AF,Sw-Pow,TV-VD,100V,2A,20W,250MHz	14h$	Hit	BD380,BD792,MJE253..254
2SB875	Si-PNP	AF,Sw-Pow,TV-VD,100V,2A,20W,250MHz	14h$	Hit	BD380,BD792,MJE253..254
2SB876	Si-PNP	AF,Sw-Pow,120/100V,1,5A,20W	14h$	Hit	2SA1021,2SA1249,2SB649
2SB877	Si-PNP	=2SB876:120/110V	14h$	Hit	2SA1021,2SA1249,2SB649
2SB878	Si-PNP	AF,Sw-Pow,180V,1,5A,10W	17j$	Hit	BD240E,2SA1011,2SB628A,2SB861..
2SB879	Si-PNP	AF,Sw-Pow,180V,1,5A,10W	17j$	Hit	BD240E,2SA1011,2SB628A,2SB861..
2SB88	Ge-PNP	=2SB85:100V	23a$	Hit	AL100..101,2N2290,2N2293..
2SB880	Si-P-Darl+Di	AF,Sw-Pow,70V,4A,30W,B=5000	17j$	Sanyo	BD718,BDW24B,BDW54B,2SB751A..
2SB881	Si-P-Darl+Di	=2SB880:7A,35W	17j$	Sanyo	BD648,BD900,BDW74B,BDX54B..
2SB882	Si-P-Darl+Di	=2SB880:10A,40W	17j$	Sanyo	BDT62A,BDT64A,BDW94B,BDX34B..

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2SB883	Si-P-Darl+Di	=2SB880: 15A, 70W	18j$	Sanyo	BDV66(A..D), BDW84(B..D)
2SB884	Si-P-Darl+Di	AF, Sw-Pow, 110V, 3A, 30W, B=4000	17j$	Sanyo	BDW24C, BDW54D, BDW64D, 2SB751B..
2SB885	Si-P-Darl+Di	=2SB884: 5A, 35W	17j$	Sanyo	BD652, BD902, BDW24C, BDW64D..
2SB886	Si-P-Darl+Di	=2SB884: 8A, 40W	17j$	Sanyo	BD652, BD902, BDW74D, BDX54D..
2SB887	Si-P-Darl+Di	=2SB884: 10A, 70W	18j$	Sanyo	BDV64C, BDW84D, 2SB913
2SB888	Si-P-Darl+Di	GenP, 80V, 0,7A, 0,6W, B=25000	7c	Sanyo	BC878, BC880, BSR61..62, 2SB865
2SB889(F)	Si-PNP	AF, Sw-Pow, 80V, 0,7A, 5W, 100MHz	14b	Rhm	(BD140, BD231, 2SA1220(A), 2SB1007,..)
2SB89(H)	Ge-PNP	AF, 25V, 0,15A, 0,25W	1a	Hit	AC128, AC151..153, AC188, 2SB475
2SB890	Si-PNP	GenP, 50V, 0,5A, 0,4W	7c	Rhm	BC327(A), BC638, BC640, 2SB910..
2SB891	Si-PNP	40V, 2A, 5W, 100MHz	-		-
2SB891(F)	Si-PNP	AF-Pow, 40V, 2A, 5W, 100MHz	14b	Rhm	2SA1359, 2SB1142..1143
2SB892	Si-PNP	AF-Dr/Out, Lo-sat, 60V, 2A, 1W, 150MHz	7c(9mm)	Sanyo	2SA1315, 2SA1706, 2SB1459
2SB893	Si-PNP	GenP, Lo-sat, 20V, 2,5A, 0,75W, 250MHz	7c	Sanyo	2SB985, 2SB1117, 2SB1300, 2SB1505..
2SB894	Si-PNP	Hi-Ueb, 30V, 0,1A, 0,45W, 150MHz	9c	Mat	2SB774, 2SB1206, (BC308, BC558..)
2SB895	Si-PNP-Darl	AF, Sw-Pow, 30V, 1A, B=8000	14h$	Mat	BD466A..B, BD876, BDX45, 2SB1008..
2SB895A	Si-PNP-Darl	=2SB895: 60V	14h$	-	BD876, BDX45..47, 2SB794..795..
2SB896	Si-PNP	AF, Sw-Pow, 40V, 10A, 35W, 150MHz	17j$	Mat	2SA1077, 2SA1291
2SB896A	Si-PNP	=2SB896: 50V	17j$	-	2SA1077, 2SA1291
2SB897	Si-P-Darl+Di	AF, Sw-Pow, 100V, ±10A, 80W, B>1000	16j$	Nec	BDV64B, BDV66A, BDW84C, TIP147
2SB898	Si-PNP	AF, Sw-Pow, 50V, 3A, 25W	17j$	Hit	BD242, BD536, BD936, 2SA1288..
2SB899	Si-PNP	AF, Sw-Pow, 50V, 3A, 25W	17j$	Hit	BD242, BD536, BD936, 2SA1288..
2SB89A(AH	Ge-PNP	=2SB89: 45V	1a	-	ACY24, ASY48, 2SB55
2SB90	Ge-PNP	AF, 18V, 5mA, 0,04W	37a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB900	Si-PNP	AF, Sw-Pow, 50V, 4A, 40W	17j$	Hit	BD536, BD540A, BD950, 2SA1289..
2SB901	Si-PNP	=2SB900: 60V	17j$	Hit	BD536, BD540A, BD950, 2SA1289..
2SB902	Si-PNP	Hi-Ueb, 30V, 0,1A, 150MHz	35a	Mat	2SA1252, (BC856..858, BCW69..70,..)
2SB903	Si-PNP	Sw, Pow, Lo-sat, 60V, 12A, 35W, 120MHz	17j$	Sanyo	2SA1328..29, (2SB826)
2SB904	Si-PNP	AF, Sw-Pow, Lo-sat, 60V, 20A, 60W, 120MHz	18j$	Sanyo	2SB1231
2SB905	Si-PNP	TV-AF-Pow, 150V, 1,5A, 10W, 50MHz	30j$	Tos	2SA1225, 2SB768, 2SB840..842..
2SB906	Si-PNP	AF, Sw-Pow, 60V, 3A, 20W, 9MHz	30j$	Tos	2SA1244, 2SB1184, 2SB1202..03
2SB907	Si-P-Darl+Di	AF, Sw-Pow, 60V, 3A, 15W, B=5000	30j$	Tos	2SB1072, 2SB1214, 2SB1303
2SB908	Si-P-Darl+Di	AF, Sw-Pow, 100V, 4A, 15W, B=5000	30j$	Tos	2SB1072, (BD902, BDW24C, BDW54C,..)
2SB909	Si-PNP	40V, 1A, 1W, 150MHz	-		-
2SB909(M)	Si-PNP	AF-Dr/Out, 40V, 1A, 1W, 150MHz	9c	Rhm	BC636, BC638, BC640, 2SB1116(A)..
2SB91	Ge-PNP	AF, 18V, 30mA, 0,04W	37a	Tos	AC125..126, AC151, 2SB54, 2SB56
2SB910(M)	Si-PNP	AF-Dr/Out, 80V, 0,7A, 1W, 100MHz	9c	Rhm	BC640, 2SA965, 2SB647, 2SB1116(A)..
2SB911(M)	Si-PNP	AF-Dr/Out, 40V, 2A, 1W, 100MHz	9c	Rhm	MPS750..751, 2SA1315, 2SA1382, 2SB892..
2SB912	Si-P-Darl+Di	AF, Sw-Pow, 70V, 10A, 60W, B=5000	18j$	Sanyo	BDV64A, BDV66A, BDW84B, TIP146..
2SB913	Si-P-Darl+Di	AF, Sw-Pow, 110V, 8A, 60W, B=4000	18j$	Sanyo	BDV64C, BDV66B, BDW84D, 2SB897..
2SB914	Si-P-Darl+Di	AF, Sw-Pow, 70V, 10A, 70W, B=5000	23a$	Sanyo	BDV64A, BDW84B, BDX86B, MJ2501..
2SB915	Si-P-Darl+Di	AF, Sw-Pow, 70V, 15A, 80W, B=5000	23a$	Sanyo	BDV66A, BDW84B, BDX66A, MJ4031..
2SB916	Si-P-Darl+Di	AF, Sw-Pow, 110V, 8A, 70W, B=4000	23a$	Sanyo	BDV64C, BDW84D, BDX62C, BDX64C..
2SB917	Si-P-Darl+Di	AF, Sw-Pow, 110V, 10A, 80W, B=4000	23a$	Sanyo	BDV64C, BDW84D, BDX64C, BDX66C..
2SB918	Si-PNP	AF/Sw-Vid, 250V, 0,5A, 0,5W	7c	Fui	BF492..493, BF423A, BFP26, MPSA92
2SB919	Si-PNP	Sw, Pow, Lo-sat, 60V, 8A, 30W, 120MHz	17j$	Sanyo	2SA1290..91, 2SB903
2SB92	Ge-PNP	AF, 32V, 0,125A, 0,125W	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB920	Si-PNP	=2SB920L: 120V	17j$	Sanyo	2SB869
2SB920L	Si-PNP	Sw, Pow, Lo-sat, 90V, 5A, 30W, 20MHz	17j$	Sanyo	2SA1293
2SB921	Si-PNP	=2SB921L: 120V	17j$	Sanyo	2SB870
2SB921L	Si-PNP	Sw, Pow, Lo-sat, 90V, 7A, 40W, 20MHz	17j$	Sanyo	2SB870
2SB922	Si-PNP	=2SB922L: 120V	18j$	Sanyo	2SB1230
2SB922L	Si-PNP	Sw, Pow, Lo-sat, 90V, 12A, 80W, 20MHz	18j$	Sanyo	2SB1230
2SB923	Si-PNP	AF, Sw-Pow, 120V, 20A, 100W	23a$	Sanyo	BD250C, BD746D
2SB924	Si-PNP	AF, Sw-Pow, 120V, 25A, 120W	23a$	Sanyo	BD250C
2SB925	Si-PNP	Lo-sat, 40V, 7A, 30W, 150MHz, 100/600nS	17j$	Mat	2SA1290..1291, 2SB919
2SB925A	Si-PNP	=2SB925: 50V	17j$	-	2SA1290..1291, 2SB919
2SB926	Si-PNP	AF-Dr/Out, Lo-sat, 30V, 2A, 0,75W	7c	Sanyo	2SB892, 2SB1229, 2SB1433..34
2SB927	Si-PNP	=2SB926: 2,5A, 1W	7c(9mm)	Sanyo	2SA1382, 2SB892, 2SB985, 2SB1312..
2SB928(A)	Si-PNP	AF, Sw-Pow, 200V, 2A, 30W, 30MHz	30j$	Mat	(2SA1133, 2SB720, 2SB861,..)
2SB929	Si-PNP	AF, Sw-Pow, 60V, 3A, 35W, 30MHz	30j$	Mat	2SB1266, 2SB1268, 2SB1270, 2SB1449,..
2SB929A	Si-PNP	=2SB929: 80V	30j$	-	2SB1270, 2SB1451
2SB93	Ge-PNP	AF, 30V, 10mA, 0,125W	1a	Mat	AC125..126, AC151, 2SB54, 2SB56
2SB930	Si-PNP	AF, Sw-Pow, 60V, 4A, 40W, 20MHz	30j$	Mat	2SB1268, 2SB1270, 2SB1449, 2SB1451
2SB930A	Si-PNP	=2SB930: 80V	30j$	-	2SB1270, 2SB1451

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2SB931	Si-PNP	AF,Sw·Pow,Lo-sat,130V,3A,30W,30MHz	30j$	Mat	-
2SB932	Si-PNP	AF,Sw-Pow,Lo-sat,130V,4A,35W,30MHz	30j$	Mat	-
2SB933	Si-PNP	AF,Sw-Pow,Lo-sat,130V,5A,40W,30MHz	30j$	Mat	-
2SB934	Si-PNP	AF,Sw-Pow,Lo-sat,130V,7A,40W,30MHz	30j$	Mat	-
2SB935	Si-PNP	AF,Sw-Pow,Lo-sat,40V,10A,35W,150MHz	30j$	Mat	-
2SB935A	Si-PNP	=2SB935:50V	30j$	-	-
2SB936	Si-PNP	AF,Sw-Pow,Lo-sat,40V,10A,40W,100MHz	30j$	Mat	-
2SB936A	Si-PNP	=2SB936:50V	30j$	-	-
2SB937	Si-P-Darl+Di	AF,Sw-Pow,60V,2A,35W,20MHz,B>1000	30j$	Mat	(BD716,BDW24A,BDW54A,2SB751,..)
2SB937A	Si-P-Darl+Di	=2SB937:80V	30j$	-	(BD718,BDW24B,BDW54B,2SB751A,..)
2SB938	Si-P-Darl+Di	AF,Sw-Pow,60V,4A,40W,15MHz,B>1000	30j$	Mat	(BD716,BDW24A,BDW54A,2SB751,..)
2SB938A	Si-P-Darl+Di	=2SB938:80V	30j$	-	(BD718,BDW24B,BDW54B,2SB751A,..)
2SB939	Si-P-Darl+Di	AF,Sw-Pow,60V,8A,45W,15MHz,B>1000	30j$	Mat	(BD646,BD898,BDW74A,BDX54A,..)
2SB939A	Si-P-Darl+Di	=2SB939:80V	30j$	-	(BD650,BD900,BDW74B,BDX54B,..)
2SB94	Ge-PNP	AF,25V,0,15A,0,15W,B>45	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB940	Si-PNP	200V,2A,35W,30MHz	-		-
2SB940(A)	Si-PNP	=2SB928(A):30W	17c	Mat	2SA1306B,2SA1668,2SB1096,2SB1530
2SB941(A)	Si-PNP	=2SB929(A):35W	17c	Mat	BDT32F,2SA1635,2SB1017,2SB1335
2SB942	Si-PNP	=2SB930(A):40W	17c	Mat	BD952F,2SA1635,2SB1017,2SB1335
2SB943	Si-PNP	=2SB931:30W	17c	Mat	2SA1650
2SB944	Si-PNP	=2SB932:35W	17c	Mat	2SA1650
2SB945	Si-PNP	=2SB933:40W	17c	Mat	2SA1650
2SB946	Si-PNP	=2SB934:40W	17c	Mat	2SA1651
2SB947	Si-PNP	=2SB935:	17c	Mat	2SA1327,2SA1567
2SB947A	Si-PNP	=2SB935A:	17c	-	2SA1327,2SA1567
2SB948	Si-PNP	=2SB936:	17c	Mat	2SA1327,2SA1567
2SB948A	Si-PNP	=2SB936A:	17c	-	2SA1327,2SA1567
2SB949	Si-P-Darl+Di	=2SB937:	17c	Mat	BDT60F,2SB1223,2SB1342
2SB949A	Si-P-Darl+Di	=2SB937A:	17c	-	BDT60AF,2SB1024,2SB1342
2SB95	Ge-PNP	=2SB94:B=60	2a	Tos	AC125..126,AC151,2SB54,2SB56
2SB950	Si-P-Darl+Di	=2SB938:	17c	Mat	BDT60F,2SB1223,2SB1342
2SB950A	Si-P-Darl+Di	=2SB938A:	17c	-	BDT60AF,2SB1024,2SB1342
2SB951	Si-P-Darl+Di	=2SB939:	17c	Mat	BD646F,BDT62F,2SB1021,2SB1224..25
2SB951A	Si-P-Darl+Di	=2SB939A:	17c	-	BD948F,BDT62AF,2SB1020..21,2SB1100
2SB952	Si-PNP	Lo-sat,40V,7A,30W,150MHz,100/600nS	30j$	Mat	2SB935..36,2SB1267(2SA1290..91,2SB919)
2SB952A	Si-PNP	=2SB952:50V	30j$	-	2SB935A..36A,2SB1267,(2SA1290..1291..)
2SB953	Si-PNP	=2SB952:	17c	Mat	2SA1470..71,2SA1643
2SB953A	Si-PNP	=2SB953:50V	17c	-	2SA1470..71,2SA1643
2SB954	Si-PNP	AF,Sw-Pow,60V,1A,30W,500/1500nS	17c	Mat	BD936F,2SB1015,2SB1094,2SB1375
2SB954A	Si-PNP	=2SB954:80V	17c	-	BD938F,BDT32AF,2SA1095,2SA1395
2SB955	Si-P-Darl+Di	AF,Sw-Pow,120V,10A,50W,B=4000	17j$	Hit	BDT62C,BDT64C,BDX34D
2SB956	Si-PNP	GenP,20V,1A,200MHz	39b	Mat	BC869,BCX51..53,BCX69,2SA1364..
2SB956-Q	Si-PNP	-	39	Mat	→2SB956
2SB956-R	Si-PNP	-	39	Mat	→2SB956
2SB956-S	Si-PNP	-	39	Mat	→2SB956
2SB956-T	Si-PNP	-	39	Mat	→2SB956
2SB957	Si-PNP	AF,Sw-Pow,100V,2A,20W,250MHz	30j$	Hit	2SA1593,2SB768,(2SB928(A))
2SB958	Si-PNP	AF,Sw-Pow,100V,2A,20W,250MHz	30j$	Hit	2SA1593,2SB768,(2SB928(A))
2SB959	Si-PNP	AF,Sw-Pow,120V,1,5A,20W	30j$	Hit	2SA1593,2SB768,(2SB928(A))
2SB96	Ge-PNP	AF,32V,0,125A,0,125W	1a	Mat	AC125..126,AC151,2SB54,2SB56
2SB960	Si-PNP	AF,Sw-Pow,120V,1,5A,20W	30j$	Hit	2SA1593,2SB768,(2SB928(A))
2SB962(Z)	Si-PNP	AF,Sw-Pow,Lo-sat,40V,3A,10W,80MHz	30j$	Nec	2SB1202..03,(2SB906,2SB1184)
2SB963(-Z)	Si-P-Darl+Di	AF,Sw-Pow,60V,±1A8W,B=2k..30k	30j$	Nec	2SB907,2SB964,2SB1214,2SB1316
2SB964	Si-P-Darl+Di	AF,Sw-Pow,60V,1,5A,10W,B=8000	30j$	Nec	2SB907,2SB1214,2SB1316
2SB965	Si-PNP	AF,Sw-Pow,120V,7A,70W,75MHz	16j$	Nec	BD246C,2SA1141,2SA1186,2SB688..
2SB966	Si-PNP	AF,Sw-Pow,120V,8A,80W,65MHz	16j$	Nec	BD246C,2SA1141,2SA1186,2SB688..
2SB967	Si-PNP	AF,Sw-Pow,27V,5A,20W,120MHz	30j$	Mat	2SA1242,2SA1244,2SA1385,2SB1203
2SB968	Si-PNP	AF,Sw-Pow,50V,1,5A,20W,150MHz	30j$	Mat	2SB838,2SB957..960,2SB1201,2SB1241
2SB969	Si-P-Darl+Di	AF,Sw-Pow,100V,15A,100W,B=5000	16j$	Nec	BDV66A,BDW84C,2SB1079
2SB97	Ge-PNP	AF,LN,18V,5mA,0,04W	37a	Tos	AC125..126,AC151r,ACY32,2SB173
2SB970	Si-PNP	GenP,15V,0,5A,130MHz	35a	Matsushita	BC807..808,BCX17..18,2SA1326..
2SB970-Q	Si-PNP	-	35	Mat	→2SB970
2SB970-R	Si-PNP	-	35	Mat	→2SB970
2SB970-S	Si-PNP	-	35	Mat	→2SB970

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2SB971	Si-PNP	AF-Dr/Out,20V,1A,1W	7c(9mm)	Mat	2SA966,2SB738..739,2SB978,2SB927
2SB972	Si-PNP	GenP,7V,0,5A	35a	Mat	BC807..808,BCX17..18,2SA1326..
2SB973	Si-PNP	GenP,10V,0,7A,280MHz	35a	Hitachi	BCW67..68,2SA1298,2SA1621
2SB973-B	Si-PNP	-	35	Hit	→2SB973
2SB973-C	Si-PNP	-	35	Hit	→2SB973
2SB974	Si-P-Darl+Di	AF,Sw-Pow,100V,5A,30W,B=6000	15j$	Nec	BD650,BD902,BDW24C,BDW64C..
2SB975	Si-P-Darl+Di	AF,Sw-Pow,100V,8A,40W,B=6000	15j$	Nec	BD650,BD902,BDW74C,BDX54C..
2SB976	Si-PNP	DC-DC-Conv.,27V,5A,0,75W,120MHz	7c	Mat	2SA1431,2SB1050,2SB1288,2SB1305..07..
2SB977	Si-PNP-Darl	GenP,30V,1A,0,75W,B>2000	7c	Mat	BC876,BC878,BSR60..62,2SB865,+
2SB977A	Si-PNP-Darl	=2SB977:60V	7c	-	BC876,BC878,BSR60..62,2SB865..
2SB978	Si-PNP	AF-Dr/Out,40V,1,5A,0,9W	7c(9mm)	Hit	2SA1315,2SA1382,2SB892,2SB1312
2SB979	Si-PNP	AF,Sw-Pow,100V,5A,60W,20MHz	18j$	Mat	BD246C,2SB688,2SB775..776,2SB695..
2SB98	Ge-PNP	AF,30V,0,05A,0,125W	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB980	Si-PNP	AF,Sw-Pow,120V,6A,70W	18j$	Mat	BD246C,2SB688,2SB776,2SB695..
2SB981	Si-PNP	AF,Sw-Pow,140V,7A,80W	18j$	Mat	BD246D,2SA1186,2SB816..817,2SB695,..
2SB982	Si-PNP	AF,Sw-Pow,150V,9A,100W	18j$	Mat	BD246D,2SA1227(A),2SA1386(A),2SB817
2SB983	Si-PNP	AF,Sw-Pow,60V,7A,40W,10MHz,200/800nS	17j$	Shi	BD244A,BD544A,BD798,2SA1290..
2SB984	Si-PNP	AF-Dr/Out,120V,1A,1W,100MHz	9b	NEC	2SA1013,2SB647,2SB1130,2SB1236..
2SB985	Si-PNP	Dr,Lo-sat,60V,3A,1W,150MHz	7c(9mm)	Sanyo	2SA1066,2SA1707
2SB986	Si-PNP	=2SB985:4A,10W	14h$	-	-
2SB987	Si-PNP	AF-Dr/Out,120V,0,5A,1W,250MHz	7c(9mm)	Mat	2SA965,2SA840,2SB647,2SB1297..
2SB988	Si-PNP	AF,Sw-Pow,60V,3A,30W,<400/2200nS	17j$	Kec	BD242A,BD536,BD936,2SA1262..
2SB989	Si-PNP	AF,Sw-Pow,80V,4A,30W,>3MHz	17j$	Kec	BD244A,BD536,BD936,2SB920L..
2SB99	Ge-PNP	AF,30V,0,05A,0,125W	2a&	Nec	AC125..126,AC151,2SB54,2SB56
2SB991	Si-PNP	AF,Sw-Pow,180V,1,5A,20W,8MHz	17j$	Sanyo	BD240E,2SB608,2SB628A,2SB630,2SB861
2SB992	Si-PNP	AF,Sw-Pow,Lo-sat,100V,7A,40W,10MHz	15j$	Tos	-
2SB993	Si-PNP	AF,Sw-Pow,Lo-sat,70V,7A,40W,10MHz	15j$	Tos	2SA1290,2SB921L
2SB994	Si-PNP	AF,Sw-Pow,60V,3A,30W,3MHz	15j$	Tos	BD242A,BD536,BD936,2SA1262..
2SB995	Si-PNP	AF,Sw-Pow,100V,5A,40W,5MHz	15j$	Tos	BD244C,BD544C,BD954,2SB633..
2SB996	Si-PNP	AF,Sw-Pow,80V,3A,30W,9MHz	15j$	Tos	BD242B,BD538,BD540B,2SB682..
2SB997	Si-P-Darl+Di	AF,Sw-Pow,100V,7A,40W,B=6000	15j$	Tos	BD650,BD902,BDW74C,BDX54C..
2SB998	Si-P-Darl+Di	AF,Sw-Pow,80V,7A,40W,B=6000	15j$	Tos	BD648,BD900,BDW74B,BDX54B..
2SB999	Si-P-Darl+Di	AF,Sw-Pow,60V,7A,40W,B=6000	15j$	Tos	BD646,BD898,BDW74A,BDX54A..
2SC100	Si-NPN	HF/Sw,40V,0,2A,0,15W,<40/70nS	24b	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC1000	Si-NPN	55V,0.1A,0.2W,80MHz	-		-
2SC1000(G)	Si-NPN	GenP,LN,55V,0,1A,0,2W,80MHz	7c	Tos	BC414,BC550,2SC2240,2SC2459..
2SC1000GTM	Si-NPN	=2SC1000:60V,0,4W	7c	-	2SC2240,2SC2459,2SC2675,2SC3378..
2SC1001	Si-NPN	UHF-Dr/Out,40V,0,5A,Pq>1,2W(470MHz)	2a*	Tos	BFS50,MRF629,2N3948,2SC2852
2SC1002	Si-NPN	UHF-Pow,36V,1A,Pq=3W(470MHz)	49a	Tos	-
2SC1003	Si-NPN	UHF-Pow,36V,2A,Pq=6W(470MHz)	49a	Tos	-
2SC1004	Si-NPN	TV-HD/VD,1100/700V,0,5A,50W	23a$	Toshiba	BU204..206,BU208A,2SC1167,2SD1095
2SC1004A	Si-NPN	=2SC1004:1500/800V	23a$	-	BU205..206,BU208A,2SD575,2SD818
2SC1005	Si-NPN	TV-HD,1100/600V,5A,50W,3MHz	23a$	Toshiba	BU207..209,2SC1413,2SD380(A)..
2SC1005A	Si-NPN	=2SC1005:1400/600V	23a$	-	BU208..209,2SD380(A),2SD792,2SD954..
2SC1006	Si-NPN	GenP,LN,50V,0,03A,0,3W,90MHz	2a$	Nec	BC184,BC414,BC550,2SC2240..
2SC1007	Si-NPN	GenP,60V,0,2A,0,3W,250MHz,95/240nS	2a$	Nec	BC174,BC182,BC190,BC546,2N3904..
2SC1008	Si-NPN	GenP,80V,0,7A,0,8W,75MHz,120/300nS	2a$	Nec,Mic	BC140..141,BC300..301,2N1889..90..
2SC1008A	Si-NPN	=2SC1008:100V	2a$	-	BC141,BC300,2N1889..90,2N2102..
2SC1009(A)	Si-NPN	HF-LN,50V,0,05A,250MHz	35a	NEC	BC846..847,BCW71..72,BCW81..
2SC1009-F1	Si-NPN	-	35	Mot,Nec	→2SC1009
2SC1009-F2	Si-NPN	-	35	Mot,Nec	→2SC1009
2SC1009-F3	Si-NPN	-	35	Mot,Nec	→2SC1009
2SC1009-F4	Si-NPN	-	35	Mot,Nec	→2SC1009
2SC1009-F5	Si-NPN	-	35	Mot,Nec	→2SC1009
2SC101	Si-NPN	HF-Pow,60V,2A,60W,16MHz	22a$	Tos	BD239A,BD241A,BD935,2SC1398..
2SC1010	Si-NPN	GenP,LN,50V,0,03A,0,3W,90MHz	2a$	Nec	BC184,BC414,BC550,2SC2240..
2SC1011	Si-NPN	VHF-A/Dr/Out,40V,0,75A,Pq=3W(150MHz)	51r	Mit	BLW17,2SC1405
2SC1012(Z)	Si-NPN	Vid,165V,0,06A,0,75W,>80MHz	2a$	Mat,Mic	BF257..259,BF657..659,2N5058..59
2SC1012A	Si-NPN	250V,60mA,0.75W,>80MHz	-		-
2SC1012A(AZ)	Si-NPN	=2SC1012:250V	2a$	-	BF258..259,BF658..659,2N5058..59
2SC1013	Si-NPN	AF,Sw-Pow,35V,1,5A,7W,70MHz	13I$	Mitsubishi	(BD507,BD517,BD525,BD839,..)
2SC1014	Si-NPN	=2SC1013:50V	13I$	Mit	(BD509,BD519,BD527,BD841,..)
2SC1015	Si-NPN	UHF-Pow,40V,3A,Pq=14W(450MHz)	55r*	Mit	BLW15,BLX69
2SC1016	Si-NPN	UHF-Dr/Out,35V,0,5A,Pq=1,3W(500MHz)	51r	Mit	BLW12,BLX66

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2SC1017	Si-NPN	AM-Out,75V,1A,Pq=0,06W(27MHz)	13I$	Mitsubishi	-
2SC1018	Si-NPN	AM-Out,75V,1A,Pq=1,4W(27MHz)	13I$	Mitsubishi	-
2SC1019	Si-NPN	UHF-Pow,60V,4A,Pq=28W(500MHz)	60c*	Mit	2N6104
2SC101A	Si-NPN	=2SC100:70V,5A,35W,20MHz	22a$	-	BD243A,BDS39B,BD9S1,2SC3253..
2SC102	Si-NPN	HF/Sw-Pow,50V,7A,100W,20MHz	38a$	Tos	(BD245,BDV91,2SC3256,2SD895..896)
2SC1020	Si-NPN	UHF-Pow,60V,8A,Pq=45W(500MHz)	60c*	Mit	-
2SC1021	Si-NPN	VHF-Pow,60V,6A,Pq=45W(90MHz)	55r	Mit	(BLX15)
2SC1022	Si-NPN	VHF-Pow,60V,6A,Pq=45W(150MHz)	55r	Mit	-
2SC1023	Si-NPN	HF,25V,25mA,200MHz	7c	Fui	BF240..241,BF254..255,BF594..595,..
2SC1024	Si-NPN	TV-VD,60V,3A,25W,8MHz	22a$	Sanyo	BD241A,BD935,2N4232,2SC3252..
2SC1025	Si-NPN	Sw,Pow,TV-HD,200V,3A,25W,8MHz	22a$	Sanyo	BU406..408,2SC1025,2SD1136,2SD1159
2SC1026	Si-NPN	HF,25V,25mA,200MHz	7c	Fui	BF240..241,BF254..255,BF594..595,..
2SC1027	Si-NPN	Sw,Pow,250/80V,6A,50W	23a$	Sanyo	BU606..608,BUX18(A..C),2SC2769..
2SC1028..1029	Si-NPN	-		Sanyo	-
2SC103(A)	Si-NPN	Sw,25(A=30)V,0,05A,0,25W,>200MHz	2a$	Tos	BC168,BC183,BC238,BC548,2N2221..
2SC1030	Si-NPN	AF-Pow,150/80V,6A,50W,10MHz	23a$	Hitachi	BD245D,2N3442,2SD551,2SD1046..
2SC1031	Si-NPN	Sw,Pow,300/300V,2A,30W,15MHz,<5/15µS	22a$	Fui,Nec	BUX67A..C,2N3584,2SC1504,2SC2023..
2SC1032	Si-NPN	HF,25V,25mA,0,15W,200MHz	7c	Fui	BF240..241,BF254..255,BF594..595,..
2SC1033	Si-NPN	Mix,Vid,200/150V,25mA,0,3W,150MHz	2a$	Mat,Mic	BF298..299,BF420,BF422,BF483..
2SC1033A	Si-NPN	=2SC1033:250/200V	2a$	-	BF298..299,BF420,BF422,BF483..
2SC1034	Si-NPN	Sw,Pow,TV-HD,1100V,1A,25W,5MHz	22a$	Son	BU505,BU208A,2SD470,2SD948,2SD1492
2SC1035	Si-NPN	VHF/UHF-Pre,LN,30V,0,02A,700MHz	5g	Sanyo	BF377..378,BF689,BF763,2N2857..
2SC1036	Si-NPN	VHF/UHF-Mix/Osc,30V,0,02A,700MHz	5g	Sanyo	BF377..378,BF689,BF763,2N2857..
2SC1037	Si-NPN	VHF-Pow,60V,4A,Pq=33W(160MHz)	49a	Nec	-
2SC1038	Si-NPN	VHF-Dr/Out,40V,0,15A,Pq=0,8W(2,3GHz)	55s	Nec	BFQ34,BFR94,BFT98,2SC1041
2SC1039	Si-NPN	VHF-Dr/Out,40V,0,25A,Pq=1,4W(2,3GHz)	55s	Nec	BFQ68,BFT98,2SC1042
2SC104(A)	Si-NPN	GenP,25(A=30)V,0,05A,0,25W,250MHz	2a$	Tos	BC168,BC183,BC238,BC548,2N2221..
2SC1040	Si-NPN	UHF-Pow,40V,1,2A,Pq>8W(500MHz)	55s	Nec	BLW91,MRF321,MRF331
2SC1041	Si-NPN	UHF-A/Dr/Out,40V,0,15A,Pq=0,9W(2GHz)	55s	Nec	BFQ34,BFR94,BFT98,2SC1038
2SC1042	Si-NPN	UHF-A/Dr/Out,40V,0,25A,Pq=1,6W(2GHz)	55s	Nec	BFQ68,BFT98,2SC1039
2SC1043	Si-NPN	UHF-A/Dr,LN,45V,0,3A,2,2GHz	55s	Nec	BFQ68
2SC1044	Si-NPN	VHF/UHF,LN,1000MHz	5g	Nec	BF377..378,BF689,BF763,2N2857..
2SC1045	Si-NPN	TV-VD,1000/550V,1A,25W	23a$	Sanyo	BU204..206,2SC1101,2SC1167,2SD1095..
2SC1046	Si-NPN	TV-HD,1000/400V,3A,25W	23a$	Sanyo	BU207..209,2SC1875,2SD819,2SD1098,..
2SC1046N	Si-NPN	=2SC1046:1200/400V	23a$	-	BU207..209,2SC1875,2SD819,2SD1098,..
2SC1047	Si-NPN	AM/FM,30V,20mA,650MHz	7c	Mat,Mic	BF225,BF310,BF314,BF502,2SC829..
2SC1048	Si-NPN	Vid,200V,0,05A,0,6W,120MHz	2a$	Mic,Say	BF258..259,BF658..659,2N5058..59
2SC1049	Si-NPN	-		Sanyo	-
2SC105	Si-NPN	GenP,30V,0,08A,0,25W,250MHz	2a$	Tos	BC168,BC183,BC238,BC548,2N2221..
2SC1050	Si-NPN	Sw,Pow,TV-VD,300/300V,1A,40W,5MHz	23a$	Sanyo	BU104,BU606..608,2SD916,2SD1154
2SC1051	Si-NPN	AF,Sw-Pow,150/100V,7A,60W,8MHz	23a$	Sanyo	BD245D,2N3442,2SD551,2SD1046..
2SC1051L	Si-NPN	=2SC1051:100/80V	23a$	-	BD245C,BDV95,2SC3181,2SD1187..
2SC1052	Si-NPN	Sw,75V,1A,0,8W,<50/70nS	2a$	Fui	BSS14,BSV95,2N3735,2N5262
2SC1053	Si-NPN	Sw,75V,0,7A,0,8W,<40/60nS	2a$	Fui	BSS14,BSV95,2N3735,2N5262
2SC1054	Si-NPN	VHF,LN,35V,0,05A,700MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC1055(H)	Si-NPN	Sw,Pow,130/80V,7A,25W,25(H=14)MHz	22a$	Hit	BU406..408,MJE15030,2SD866..
2SC1056	Si-NPN	Vid,260/260V,0,1A,0,75W,180MHz	2a$	Son	BF258..259,BF658..659,2N5058..59
2SC1057	Si-NPN	UHF-Pow,50V,1A,Pq=6,5W(700MHz)	55r	Fui	-
2SC1058	Si-NPN	UHF-Pow,50V,2A,Pq=11,5W(700MHz)	55r	Fui	-
2SC1059	Si-NPN	AF/Vid-Pow,300/300V,0,15A,8W(Tc=70°)	22a$	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC106	Si-NPN	HF/Sw-Pow,60V,2A,15W,100MHz,-/230nS	2a$	Tos	(BD137,BD228,BD377,2SD794(A),..)
2SC1060	Si-NPN	AF,Sw-Pow,50V,3A,25W,8MHz	17j$	Hit,Mic	BD241,BDS3S,BD93S,TIP31A,2SC3252..
2SC1061(K)	Si-NPN	AF,Sw-Pow,50V,3A,25W,8MHz	17j$	-	BD241,BD535,BD935,2SC3252..
2SC1062	Si-NPN	Sw,Vid,200/200V,0,1A,0,7W,35MHz	2a$	Fui,Nec	BF258..259,BF658..659,2N5058..59
2SC1063	Si-NPN	Sw,10V,1A,0,75W,<60/100nS	2a$	Son	BSS28..29,BSX12,2N3426,2N3724A..
2SC1064	Si-NPN	Sw,60V,1A,0,8W	2a$	old	BSS13,BSS27,BSV77,2N3735..
2SC1065	Si-NPN	Sw,90V,1A,0,8W,400MHz	2a$	old	(BSV95,2N3735)
2SC1066	Si-NPN	UHF,20V,25mA,800MHz	2a$	Fui	BF377..278,BF689,BF763,2N2857..
2SC1067	Si-NPN	VHF,35V,0,05A,500MHz	2a	Fui	BF225,BF310,BF314,BF502,2SC1856+
2SC1068	Si-NPN	UHF,CATV,25V,0,15A,0,5W,2000MHz	2a	Fui	BFR36,BFW16,2SC2852
2SC1069	Si-NPN	Sw,100V,1A,0,8W,<60/120nS	2a$	Fui	-
2SC107	Si-NPN	=2SC106:1,5A	2a$	Tos	(BD137,BD228,BD377,2SD794(A),..)
2SC1070	Si-NPN	UHF-Pre-in,30V,0,02A,900MHz	25u	Nec	2SC2144,2SC2353,2SC2464,2SC2466..
2SC1071	Si-NPN	Sw,30V,0,2A,0,3W,<45/42nS	2a$	Fui,Hit,Nec	BSS11..12,BSX19..20,2N2368..69(A),..

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2SC1072(A)	Si-NPN	Sw,60V,0,7A,0,8W,<40/60nS	2a$	Fui,Hit,Nec	BSS13,BSS27,BSV77,2N5189..
2SC1073(Z)	Si-NPN	UHF-Dr/Out,36V,0,5A,Pq=1,8W(500MHz)	55r*	Mat	BLW42,BLW79,BLX67,BLY38,2N5945
2SC1074(Z)	Si-NPN	UHF-Dr/Out,36V,1A,Pq=4W(500MHz)	55r*	Mat	BLW43,BLW80
2SC1075(Z)	Si-NPN	UHF-Pow,36V,2A,Pq=8W(500MHz)	55r*	Mat	BLW14,BLW44,2N5946
2SC1076(Z)	Si-NPN	UHF-Pow,36V,3A,Pq=15W(500MHz)	55r*	Mat	BLW15,BLX69
2SC1077(A)	Si-NPN	VHF-Pow,65V,5..6A,Pq=42W(175MHz)	55r	Tos	BLW25,BLY94,2N5643
2SC1078	Si-NPN	Sw,Pow,700/500V,0,5A,20W,2MHz	22a$	Tos	BU208A,MJ4361,2SC1810,2SC1828,2SC3352
2SC1079	Si-NPN	AF,Sw-Pow,150/150V,12A,100W,4MHz	23a$	Tos	BDW12,2SC1584,2SD551,2SD733..
2SC108	Si-NPN	HF/Sw,90V,0,6A,0,6W,>100MHz	2a$	Tos	BC300..301,BC141,BSW39,2N1990..
2SC1080	Si-NPN	=2SC1079:110/100V	23a$	Tos	BD545D,BDW10,BDW51C,2SD551,2SD1105..
2SC1081	Si-NPN	UHF-Pow,40V,2,5A,Pq=14W(500MHz)	55s*	Nec	BLW15,BLX69
2SC1082	Si-NPN	UHF-Dr/Out,50V,0,5A,Pq=3W(700MHz)	55r	Fui	2N4430
2SC1083(F)	Si-NPN	UHF-A/Dr/Out,40V,0,5A,1600MHz	2a$	Fui	BFS50,MRF629,2N3948
2SC1084	Si-NPN	GenP,35V,0,05A,0,25W,300MHz	2a$	Fui	BC168,BC183,BC238,BC548,2SC1890+
2SC1085	Si-NPN	GenP,30V,0,1A,0,2W,230MHz	2a$	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1086	Si-NPN	TV-HD,1000V,4A,125W,5MHz	23a$	Sony	BU207..209,2SC1348-1..-3,2SC1413..
2SC1087	Si-NPN	UHF-Pow,45V,3A,Pq=16W(700MHz)	55r	Fui	-
2SC1088	Si-NPN	AF-Out/Vid,300/200V,0,1A,12,5W,>30MHz	17j$	Mit	2SC1505..1507,2SC1755..1757,2SC1819,MJE3440...
2SC1089	Si-NPN	=2SC1088:300/300V	17j$	Mit	2SC1505..1507,2SC1755..1757,2SC1819,MJE3440...
2SC108A	Si-NPN	=2SC108:0,8A,0,8W	2a$	-	BC300..301,BC141,BSW39,2N1990..
2SC109	Si-NPN	HF/Sw,50V,0,6A,0,6W,>70MHz	2a$	Tos	BC140..141,BC300..302,BSW39..
2SC1090	Si-NPN	UHF-A,20V,0,05A,0,3W,3GHz	51s	Nec	BFQ72
2SC1091	Si-NPN	-		Nec	-
2SC1092	Si-NPN	GenP,150/120V,0,7A,0,8W	2a$	Nec	BSS43,BSW68,2SC1860
2SC1093	Si-NPN	-		Nec	-
2SC1094	Si-NPN	-		Nec	-
2SC1095	Si-NPN	AF,Sw-Pow,30V,2A,10W,60MHz	13j$	NEC	2SC1226,2SC1848,(BD505,BD507..)
2SC1096(L,Z)	Si-NPN	AF,Sw-Pow,40V,3A,10W,60MHz	13j$	NEC	2SC1226,(BD429,BD613,BD813,..)
2SC1097	Si-NPN	AF,Sw-Pow,60V,1A,10W,60MHz	13j$	NEC	2SC1848,(BD385,BD415,BD827..)
2SC1098(A)(L,Z)	Si-NPN	AF,Sw-Pow,70V,3A,10W,60MHz	13j$	NEC	(BD619)
2SC1099	Si-NPN	TV-HD,1200/400V,3A,50W	23a$	NEC	BU207..209,2SC1413,2SD1098,2SD1102..
2SC109A	Si-NPN	=2SC109:70V	2a$	-	BC140..141,BC300..302,BSW39..
2SC11	Ge-NPN	Sw,18V,24mA,0,055W,60/140nS	2a	Tos	ASY28..29
2SC110	Si-NPN	GenP,40V,0,2A,0,75W,160MHz	2a$	Hit	BC140..141,BSV69,2N3723..3725..
2SC1100	Si-NPN	=2SC1099:1100/400V	23a$	Nec	BU207..209,2SC1413,2SD1098,2SD1102..
2SC1101	Si-NPN	TV-VD,1100/500V,1A,50W	23a$	NEC	BU204..206,2SC1132,2SC1167,2SD1095..
2SC1102	Si-NPN	CTV-Vid-Out.,300/300V,0,05A,11W,>60MHz	22a$	Nec	2SC1505..1507,2SC1755..1757,2SC1819,..
2SC1103(A)	Si-NPN	Vid,250/250V,0,1A,0,8W,80MHz	2a$	Nec	BF258..259,BF658..659,2N5058..59
2SC1104	Si-NPN	CTV-AF-Pow,Sw,300/300V,0,7A,20W	22a$	Nec	TIP47..50,2N3739,2SC782,2SC1929..
2SC1105	Si-NPN	CTV-HD-Driver,300V,0,1A,15W,20MHz	22a$	Nec	2SC1505..1507,2SC1755..1757,2SC1819,..
2SC1106	Si-NPN	Sw,Pow,CTV-SN,350/250V,2A,80W	23a$	Nec	BU126,BU326A,2SC1295
2SC1107	Si-NPN	AF,Sw-Pow,80V,4A,25W,10MHz	17j$	Sak	BD243B,BD537,BD951,2SC3179..
2SC1108	Si-NPN	=2SC1107:100V	17j$	Sak	BD243C,BD539C,BD953,2SD613..
2SC1109	Si-NPN	=2SC1107	17j$	Sak	2SC1107,BD243B
2SC111	Si-NPN	GenP,50V,0,2A,0,75W,160MHz	2a$	Hit	BC140..141,BSV77,2N3723..3725..
2SC1110	Si-NPN	=2SC1108	17j$	Sak	2SC1108,BD243C
2SC1111	Si-NPN	AF,Sw-Pow,140/80V,6A,50W,10MHz	23a$	Sak	BD245D,BUV50,2N3442,2SD551,2SD1046..
2SC1112	Si-NPN	=2SC1111:160/100V	23a$	Sak	BD245D,2N3442,2SD551,2SD1046..
2SC1113	Si-NPN	AF,Sw-Pow,120/100V,6A,40W,10MHz	22a$	Sak	BD243C,BD543D,MJE15028,2SD866
2SC1114	Si-NPN	Sw,Pow,300/325V,4A,100W,10MHz	23a$	Sanken	BU326A,BU606..608,BUW71,BUX16A..C..
2SC1115	Si-NPN	Sw,Pow,140/80V,10A,100W,10MHz	23a$	Sanken	BD245D,BUV50,2N3442,2SD551,2SD1047..
2SC1116	Si-NPN	=2SC1115:180/120V	23a$	Sak	BD245E,BDW14,BDY54,BUV21,2SC3263..
2SC1116A	Si-NPN	=2SC1115:200/140V	23a$	-	MJ15015,BD245F,2SC1585,2SC2608..
2SC1117(H)	Si-NPN	UHF,20V,0,02A,850MHz	5g	Hit	BF377..378,BF689,BF763,2N2857..
2SC1118	Si-NPN	UHF-Pow,45V,2A,Pq=14,5W(500MHz)	55s	Nec	BLW94,BLX94,MRF323
2SC1119	Si-NPN	UHF,LN,20V,0,03A,0,25W,4,5GHz	51s	Nec	BFQ71,BFQ85,BFR14,BFR91
2SC112	Si-NPN	GenP,40V,0,2A,0,75W,180MHz,-/127nS	2a$	Hit	BC140..141,BSV69,2N3723..3725..
2SC1120	Si-NPN	UHF-Pow,35V,1,5A,Pq=4W(470MHz)	55r	Tos	BLW13..14,BLW43,BLX68,BLY53
2SC1121	Si-NPN	UHF-Pow,35V,3A,Pq=8,5W(470MHz)	55r	Tos	BLW15,BLW81,BLX69
2SC1122(A)	Si-NPN	UHF-Pow,35V,4,5A,Pq=14W(470MHz)	55r	Tos	BLW15,BLX69
2SC1123	Si-NPN	FM/VHF,35V,0,1A,550MHz	7e	Son	BF225,BF310,BF314,BF502,2SC1393+
2SC1124	Si-NPN	AF/HF/Sw-Pow,140/140V,1A,7,9W,120MHz	13g$	Sony	2SC2384,(2SC1913,2SC2481,2SC2483..)
2SC1125	Si-NPN	-		Son	-
2SC1126	Si-NPN	FM/VHF,550MHz	7f	Son	BF225,BF310,BF314,BF502,2SC1393+

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2SC1127-1,-2	Si-NPN	AF/Vid-Out,180..210V,0,1A,7,9W	13g$	Sony	BF460..462,MPSU10,2SC2224(A)..
2SC1128	Si-NPN	FM/VHF,35V,0,1A,550MHz	7f	Son	BF370,BF921S,BF959
2SC1129	Si-NPN	FM/VHF,35V,0,03A,400MHz	7f	Son	BF370,BF921S,BF959
2SC113	Si-NPN	GenP,50V,0,2A,0,75W,180MHz,<-/127nS	2a$	Hit	BC140..141,BSV77,2N3723..3725..
2SC1130	Si-NPN	Sw,Pow,800/400V,3,5A,80W,4MHz,<1/2µS	23a$	Org	BU326(A),BU426(A),BUS11,BUX46..
2SC1131	Si-NPN	=2SC1130:600/300V	23a$	Org	BU326(A),BU426(A),BUS11,BUX46..
2SC1132	Si-NPN	Sw,Pow,TV-HD,1200/500V,2,5A,30W	23a$	Org	BU204..206,2SC1875,2SD1097..1098..
2SC1133	Si-NPN	Sw,Pow,TV-HD,1200/500V,5A,80W,4MHz	23a$	Org	BU207..209,2SC1413,2SD1103..1104..
2SC1134..1135	Si-NPN	-		Org	-
2SC1136	Si-NPN	Sw,Pow,200/150V,30A,200W,9MHz	68a$	Org	2SC2128,2SC2940,2SC3224,2SD540..541..
2SC1137	Si-NPN	-		Org	-
2SC1138	Si-NPN	Sw,Pow,800/400V,30A,200W,9MHz	68a$	Org	2SC2204,2SC2977,2SD295
2SC1139	Si-NPN	=2SC1138:600/300V	68a$	Org	2SC2204,2SC2442,2SC2977,2SD644
2SC114	Si-NPN	GenP,50V,0,2A,0,75W,80MHz,<-/135nS	2a$	Hit	BC140..141,BSV77,2N3723..3725..
2SC1140	Si-NPN	Sw,Pow,800/400V,15A,150W,10MHz	23a$	Org	BUS13(A),BUW45..46,BUX48(A..C)
2SC1141	Si-NPN	=2SC1140:600/300V	23a$	Org	BUS13(A),BUW45..46,BUX48(A..C)
2SC1142	Si-NPN	Sw,Pow,800/400V,10A,125W,4MHz	23a$	Org	BUS12(A),BUW26,BUW35..36,BUX80,..
2SC1143	Si-NPN	=2SC1142:600/300V	23a$	Org	BUS12(A),BUW25..26,BUW35,BUX80,..
2SC1144	Si-NPN	Sw,Pow,400/250V,30A,200W,9MHz	68a$	Org	2SC1302,2SC1401,2SD542..543..
2SC1145	Si-NPN	Sw,Pow,700/400V,20A,175W,9MHz	68a$	Org	2SC2204,2SC2977,2SD295
2SC1146..1149	Si-NPN	-		Org	-
2SC115	Si-NPN	GenP,30V,0,05A,0,75W,200MHz	2a$	Son	BC168,BC183,BC238,BC548,2N2218..
2SC1150	Si-NPN	Sw,60V,1A,0,8W,<35/55nS	2a$	Fui	BSS13,BSS27,BSV77,2N5189..
2SC1151	Si-NPN	Sw,Pow,TV-VD,900/450V,1A,50W,5MHz	23a$	Mitsubishi	BU204..206,2SC1101,2SC1167,2SD1095..
2SC1151A	Si-NPN	=2SC1150:1000/580V	23a$	-	BU204..206,2SC1101,2SC1167,2SD1095..
2SC1152	Si-NPN	Sw,Pow,TV-VD,300/300V,2,5A,50W,5MHz	23a$	Mitsubishi	(BU126)
2SC1153	Si-NPN	TV-HD,1200/500V,2,5A,50W	23a$	Mitsubishi	BU204..206,2SC1132,2SD1097..1098..
2SC1153A	Si-NPN	=2SC1153:1400/500V	23a$	-	BU205..206,2SC1922,2SD575,2SD818..
2SC1154	Si-NPN	=2SC1153:3,5A	23a$	Mit	BU207..209,2SC1875,2SD517,2SD819..
2SC1155	Si-NPN	AF/HF/Sw-Pow,70V,0,8A,7W,70MHz	13l$	Mitsubishi	(BD417,BD519,BD527,BD529,..)
2SC1156	Si-NPN	=2SC1155:90V	13l$	Mit	(BD419,BD529,BD829,BD843,..)
2SC1157	Si-NPN	=2SC1155:110V	13l$	Mit	(BD419,BD529,BD829,BD843,..)
2SC1158	Si-NPN	UHF-Osc,35V,0,02A,>850MHz	24b	Nec	BF362..363
2SC1159	Si-NPN	=2SC1158:>600MHz	24b	Nec	BF362..363
2SC116(H)	Si-NPN	GenP,50V,0,2A,0,75W,120MHz	2a$	Hit	BC140..141,BC300..302,2N3053..
2SC1160	Si-NPN	TV-VD,200/100V,1A,15W,20MHz	22a$	Nec	BD239F,2SC783,2SC2238B,2SD1138..
2SC1161	Si-PNP	160V,12A,120W,	-		-
2SC1161(A)	Si-NPN	=2SC1160:200/120(A=200/140)V	22a$	Nec	BD239F,2SC783,2SC2238B,2SD1138..
2SC1162	Si-NPN	35V,1.5A,10W,180MHz	-		-
2SC1162(WT)	Si-NPN	AF,Sw-Pow,35V,2,5A,10W,180MHz	14h$	Hit	BD375,2SC2877,2SD1380,2SD1818..
2SC1163	Si-NPN	AF/Vid-Pow,300V,0,1A,20,8W,55MHz	14h$	Mat	BF459,MJE340,MJE3440,2SC2376
2SC1164	Si-NPN	UHF-A,50V,0,3A,0,6W,1400MHz	5g	Tos	BFR36,2SC2852
2SC1165	Si-NPN	UHF-Dr/Out,40V,0,5A,Pq=1W(470MHz)	2a	Tos	BFS50,MRF629,2N3948
2SC1166	Si-NPN	GenP,60V,0,2A,0,6W,120MHz	9b	Toshiba	BC174,BC182,BC190,BC546,2SD767..
2SC1167	Si-NPN	TV-HD,1200V,1,5A,50W,3MHz	23a$	Toshiba	BU204..206,2SC1132,2SD1095,2SD1097..
2SC1168	Si-NPN	Vid-Pow,300/300V,0,15A,12,5W,100MHz	22a$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC1169	Si-NPN	VHF-Dr/Out,40V,1A,Pq>2,5W(175MHz)	43a*	Tos	(2SC2989)
2SC116T	Si-NPN	=2SC116:75V	2a$	-	BC140..141,BC300..301,2N1613..
2SC117(H,T)	Si-NPN	HF/Sw-Pow,75V,0,6A,13W,112MHz	2a$	Hit	(BD139,BD230,2SD1200,2SD1378,..)
2SC1170	Si-NPN	TV-HD,1200/500V,3,5A,50W,4MHz	23a$	Toshiba	BU207..209,2SC1413,2SC1875,2SD1098..
2SC1170A	Si-NPN	=2SC1170:1400/500V	23a$	-	BU208..209,2SC1875,2SD849..850..
2SC1170B	Si-NPN	=2SC1170:1500/500V	23a$	-	BU208..209,2SD783,2SD849..850..
2SC1171	Si-NPN	TV-VD,1100V/800V,1A,50W,2MHz	23a$	Toshiba	BU204..206,2SC1101,2SC1167,2SD1095
2SC1172	Si-NPN	TV-HD,1500/600V,5A,50W,3MHz	23a$	Toshiba	BU208(A),2SC2928,2SD792,2SD820..
2SC1172A	Si-NPN	=2SC1172:6A	23a$	-	BU508(A),2SC3025..26,2SD649,2SD821
2SC1172B	Si-NPN	=2SC1172:7A	23a$	-	BU508(A),2SC3027..28,2SD822,2SD1016
2SC1173	Si-NPN	AF,Sw-Pow,30V,3A,10W,100MHz	17J$	Mic,Tos	2SC2562,2SC3252..3253,2SD1505
2SC1174	Si-NPN	TV-HD,1200/500V,3,5A,50W,4MHz	23a$	Hitachi	BU207..209,2SC1413,2SC1875,2SD1098..
2SC1175(NP)	Si-NPN	GenP,50V,0,2A,0,3(NP=0,4)W,170MHz	7c	Sanyo	BC167,BC182,BC237,BC547,2SC3377..
2SC1176	Si-NPN	VHF-Pow,40V,1A,Pq=7,5W(175MHz)	55r	Mit	BLW18,BLW37,BLY62,BLY87
2SC1177	Si-NPN	VHF-Pow,40V,2,5A,Pq=16W(175MHz)	55r	Mit	BLW29,BLY84,BLY88,MRF226,2N6081
2SC1178(A)	Si-NPN	VHF-Pow,40V,5A,Pq=23W(175MHz)	55r	Mit	BLW20,BLW31
2SC1179	Si-NPN	-		Sanyo	-
2SC118(H)	Si-NPN	HF/Sw-Pow,80V,0,6A,13W,120MHz	2a$	Hit	(BD139,BD230,2SD1200,2SD1378,..)

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2SC1180	Si-NPN	UHF,30V,0,02A,800MHz	5g	Sanyo	BF377..378,BF689,BF763,2N2857..
2SC1181	Si-NPN	HF/AF,40V,0,05A,0,3W,400MHz	-	Sanyo	BF198..199,BF224..225,2SC1855..56,..
2SC1182	Si-NPN	=2SC1181:25V	-	Sanyo	BF198..199,BF224..225,2SC1855..56,..
2SC1183	Si-NPN	-		Son	-
2SC1184	Si-NPN	TV-VD,900/500V,1A,50W	23a$	NEC	BU204..206,2SC1101,2SC1167,2SD1095..
2SC1185	Si-NPN	Sw,Pow,300/250V,0,7A,50W	23a$	NEC	2SC1106,2SC2809
2SC1186	Si-NPN	-		Nec	-
2SC1187	Si-NPN	TV-IF,40V,25mA,700MHz	7f	Nec	BF198,BF225,BF310,2SC1855..56..
2SC1188	Si-NPN	TV-IF,40V,0,03A,850MHz	7f	Nec	BF199,BF224,BF311,2SC1855..56..
2SC1189	Si-NPN	TV-IF,50V,25mA,850MHz	7f	Nec	BF199,BF224,BF311,2SC1855..56..
2SC119(H)	Si-NPN	HF/Sw-Pow,75V,0,6A,13W,130MHz	2a$	Hit	(BD139,BD230,2SD1200,2SD1378,..)
2SC1190(Z)	Si-NPN	VHF-Pow,36V,2,5A,Pq=16W(175MHz)	55r*	Mat	BLW29,BLY84,BLY88,MRF226,2N6081
2SC1191(Z)	Si-NPN	VHF-Pow,36V,3,5A,Pq=27W(175MHz)	60c*	Mat	-
2SC1192(Z)	Si-NPN	VHF-Pow,36V,5A,Pq=37W(175MHz)	60c*	Mat	-
2SC1193	Si-NPN	UHF,LN,20V,0,03A,0,2W,4,5GHz	24d	Tos	BFQ71,BFQ85,BFR14,BFR91
2SC1194	Si-NPN	-		Tos	-
2SC1195	Si-NPN	Sw,Pow,200V,2,5A,100W	23a$	Toshiba	TIP51..54,2SD632
2SC1196	Si-NPN	UHF-Pow,60V,0,75A,Pq>3W(700MHz)	55r	Tos	2N4430,2SC1082
2SC1196A	Si-NPN	=2SC1196:45V,1A,Pq>4W(700MHz)	55r	-	-
2SC1197	Si-NPN	UHF-Pow,60V,2A,Pq>9W(700MHz)	55r	Tos	-
2SC1197A	Si-NPN	=2SC1197:45V,Pq>12W(700MHz)	55r	-	-
2SC1198	Si-NPN	UHF-Pow,45V,3,5A,Pq>18W(700MHz)	55r	Tos	-
2SC1199	Si-NPN	UHF-A/Dr,LN,50V,0,3A,0,6W,1400MHz	5g	Tos	BFS50,MRF515,2SC2852
2SC12	Si-NPN	AF,Sw,60V,0,25A,0,18W,13MHz	2a	Tos	BC140..141,BC300..302,2N3053..
2SC120	Si-NPN	GenP,40V,25mA,0,25W,200MHz,B>20	2a$	Nec	BC167,BC182,BC237,BC547,2N2218..
2SC1200	Si-NPN	UHF-Dr/Out,40V,0,18A,Pq=1,06W(2GHz)	-	Tos	-
2SC1201..1203	Si-NPN	-		Tos	-
2SC1204	Si-NPN	GenP,30V,0,1A,0,31W,230MHz	9a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1205	Si-NPN	AM/FM,30V,0,1A,230MHz	9a	Hit	BF240..241,BF254..255,BF594..595,..
2SC1206(A,B)	Si-NPN	UHF-Pow,45V,1,7A,Pq=10..12W(770MHz)	55r	Mit	-
2SC1207(A,B)	Si-NPN	UHF-Pow,45V,3A,Pq=16..21W(770MHz)	55r	Mit	-
2SC1208(A)	Si-NPN	VHF-Pow,36V,10A,Pq=37..39W(175MHz)	55r	Mit	BLW60,BLY90
2SC1209	Si-NPN	GenP,25V,0,7A,0,5W,150MHz	7b	Mit	BC337..338,BC635,BC637,2SD1578..
2SC121	Si-NPN	=2SC120:130MHz,B=20..75	2a$	Nec	BC167,BC182,BC237,BC547,2N2218..
2SC1210	Si-NPN	=2SC1209:45V,0,3A	7b	Mit	BC337,BC635,BC637,2SC3377..
2SC1211	Si-NPN	=2SC1209:65V,0,3A	7b	Mit	BC337A,BC637,BC639,2SC4412..
2SC1212	Si-NPN	AF,Sw-Pow,50V,1A,8W,160MHz	14h$	Hit	BD137,BD228,BD375,2SD1177..1178
2SC1212A	Si-NPN	=2SC1212:80V	14h$	-	BD139,BD230,BD379,2SD1177..1178
2SC1213	Si-NPN	GenP,35V,0,5A,0,4W,120MHz	9b,7c	Hit	BC337..338,BC635,BC637,2SC3377..
2SC1213A(AK)	Si-NPN	=2SC1213:50V	9b,7c	Hit	BC337,BC635,BC637,2SC4414..
2SC1213C	Si-NPN	GenP,50V,0.5A,0.4W	-		-
2SC1214	Si-NPN	GenP,50V,0,5A,0,6W,50MHz	9b,7c	Hit	BC337,BC635,BC637,2SC4414..
2SC1215	Si-NPN	30V,50mA,0.4W,1.2GHz	-		-
2SC1215(S,T)	Si-NPN	VHF,30V,50mA,1200(S:>600,T:>9MHz)	7c	Mat	BF377..378,BF689K,BF763,2SC3037,..
2SC1216	Si-NPN	Sw,40V,0,2A,0,3W,<20/40nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC1217	Si-NPN	Sw,Vid,150V,0,3A,0,75W,250MHz	2a$	Nec	BSS43,BSW68,2SD413,2SD576,2SD624
2SC121B	Si-NPN	AF,Sw,80V,0,5A,0,75W,370MHz	2a$	Nec	BSW39,2N3444,2N3723,2SC1069
2SC1219	Si-NPN	GenP,30V,0,5A,0,2W,60MHz	7c	Fui	BC337..338,BC635,BC637,2SC3377..
2SC122	Si-NPN	=2SC120:160MHz,B=50..150	2a$	Nec	BC167,BC182,BC237,BC547,2N2219..
2SC1220(F)	Si-NPN	=2SC1219:50V	7c	Fui	BC337A,BC637,2SC3939,2SD1226..
2SC1222	Si-NPN	GenP,LN,50V,0,02A,0,25W,>30MHz	7c	Nec	BC184,BC414,BC550,2SC2390..
2SC1223	Si-NPN	VHF/UHF-A/Dr,30V,0,5A,0,8W,1300MHz	2a$	Mit	BFS50,MRF515,2N3948,2SC2852
2SC1224	Si-NPN	AF,Sw-Pow,130V,0,8A,7W,<200/1200nS	13l$	Mitsubishi	(2SC2483)
2SC1225	Si-NPN	-		Mit	-
2SC1226	Si-NPN	50/40V,2A,10W,150MHz	-		-
2SC1226(A)	Si-NPN	AF,Sw-Pow,40(A=50)V,2A,10W,150MHz	13j$	Matsushita	2SC1848,(BD507,2SD1206,2SD1818..)
2SC1227(F)	Si-NPN	Sw,Pow,300/200V,10A,100W,27MHz	23a$	Fujitsu	BUW24,BUW72,BUX17A..C,2SC2537..
2SC1228(F)	Si-NPN	Sw,Pow,500/400V,10A,100W,15MHz	23a$	Fujitsu	BUW25,BUW34,BUW75,2SC3043..
2SC1229	Si-NPN	=2SC1227:250/200V	23a$	Fui	BUW24,BUW72,BUX17(A..C),2SC2537,..
2SC123	Si-NPN	=2SC120:180MHz,B=80..200	2a$	Nec	BC167,BC182,BC237,BC547,2N2219..
2SC1230	Si-NPN	=2SC1228:450/400V	23a$	Fui	BUW24..25,BUW72,BUW75,2SC3043..
2SC1231	Si-NPN	Fast-Sw,20V,0,2A,0,3W,<-/27nS	2a$	Fui	BSS11..12,BSY17..18,2N3011..
2SC1232	Si-NPN	UHF-Pow,45V,1A,Pq=6W(770MHz)	55r	Fui	-
2SC1233	Si-NPN	UHF-Pow,45V,2A,Pq=11W(770MHz)	55r	Fui	-

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2SC1235	Si-NPN	AF-Pow-Vid-, 300V, 0,1A, 6,5W(Tc=70°)	22a$	Sanyo	2SC1505..1507, 2SC1755..1757, 2SC1819
2SC1236	Si-NPN	UHF, LN, 20V, 0,03A, 0,2W, 6,5GHz	24d	Tos	BFQ57..58, BFQ74, 2SC1923
2SC1237	Si-NPN	AM-Pow, 85V, 2A, Pq=3,5W(27MHz)	17j$	Tos	2SC1306, 2SC1678..1679, 2SC1909..
2SC1238	Si-NPN	UHF-A/Dr, 35V, 0,15A, 5W, 1700MHz	55r	Mit	BLV90, MRF838A
2SC1239	Si-NPN	AM-Dr/Out, 80V, 4A, Pq=3,4W(27MHz)	43a$	Mit	(2SC1306, 2SC1909, 2SC2078, 2SC2092,..)
2SC124	Si-NPN	=2SC120: 200MHz, B>20	2a$	Nec	BC167, BC182, BC237, BC547, 2N2218..
2SC1240	Si-NPN	HF, 40V, 0,05A, 0,35W, 600MHz	7b	Mit	BF198..199, BF224..225, BF310..311,..
2SC1241	Si-NPN	VHF-Pow, 40V, 1,5A, Pq>6W(175MHz)	55r*	Tos	BLW19, BLW37, MRF212, 2N5590
2SC1241A	Si-NPN	=2SC1241: 35V, 2A, Pq>8W(175MHz)	55r	-	BLW19, BLW37, MRF212, 2N5590
2SC1242	Si-NPN	VHF-Pow, 40V, 3A, Pq>13W(175MHz)	55r*	Tos	BLY89, MRF209, 2N5591, 2N6082
2SC1242A	Si-NPN	=2SC1242: 35V, 4,5A	55r*	-	BLY89, MRF209, 2N5591, 2N6082
2SC1243	Si-NPN	AF, Sw-Pow, 25V, 1,5A, 7W, 70MHz	13l$	Mitsubishi	(BD429, BD505, BD515, BD839,..)
2SC1244	Si-NPN	GenP, Sw, 30V, 0,05A, 0,2W	7b	Mit	BC168, BC183, BC238, BC548, 2SC1890+
2SC1245	Si-NPN	-		Mit	-
2SC1246(A,F,AF)	Si-NPN	GenP, 30V, 0,5A, 0,4(A=0,5)W, 60MHz	7c	Fui	BC337..338, BC635, BC637, 2SC3377..
2SC1247(A,F,AF)	Si-NPN	=2SC1246: 50V	7c	Fui	BC337, BC637, BC639, 2SD1226..
2SC1247A	Si-NPN	50V, 0.5A, 0.4W, 60MHz	-		-
2SC1248(R)	Si-NPN	UHF, LN, 20V, 0,03A, 2,5GHz	51r	Nec	BFQ59, BFQ70, BFR34, BFT97, 2SC2143
2SC1249(R)	Si-NPN	UHF-Dr/Out, 45V, 0,3A, 1,7GHz	55r	Nec	BFQ68, 2SC1043, 2SC1251
2SC125	Ge-NPN	VHF/UHF, 20V, 10mA, 700MHz	1g	Hit	-
2SC125[Sony]	Si-NPN	HF/Sw, 100V, 0,05A, 0,75W, 200MHz	2a$	Son	BF257..259, 2SC1890A, 2SC3245, 2SD755..
2SC1250(R)	Si-NPN	=2SC1249: 1,9GHz	55r	-	BFQ68, 2SC1043, 2SC1251
2SC1251	Si-NPN	UHF-A/Dr/Out, 45V, 0,3A, 7W, 2,2GHz	55s	Nec	BFQ68, 2SC1043, 2SC1250
2SC1252	Si-NPN	VHF-A/Dr, 45V, 0,3A, 0,8W, 1,7GHz	2a	Nec	2SC1199, 2SC2852
2SC1253	Si-NPN	UHF-A/Dr, 45V, 0,3A, 0,8W, 2GHz	2a	Nec	2SC1199, 2SC2852
2SC1254	Si-NPN	VHF/UHF, 45V, 0,03A, 1000MHz	5g	Nec	BF377..378, BF689, BF763, 2N2857..
2SC1255	Si-NPN	UHF-A/Dr/Out, 30V, 0,1A, 3,5W, 2,7GHz	55s	Nec	BFQ34, BFR94, 2SC1592
2SC1256	Si-NPN	VHF/UHF-Dr/Out, 36V, 0,8A, Pq=3W(175MHz)	2a$	Nec	BFQ43, BFS22, BLY33, MRF237
2SC1257	Si-NPN	VHF/UHF-Pow, 36V, 1,5A, Pq=8W(175MHz)	55s	Nec	BLW19, BLW37, MRF212, 2N5590
2SC1258	Si-NPN	VHF/UHF-Pow, 36V, 3A, Pq=14W(175MHz)	55s	Nec	BLY89, MRF209, 2N5591, 2N6082
2SC1259	Si-NPN	VHF/UHF-Pow, 36V, 6A, Pq=30W(175MHz)	55s	Nec	BLW20, BLW31, 2N6084
2SC126	Si-NPN	=2SC125[Sony]: 140V	2a$	Son	BF257..259, 2SC2375, 2SC3245A, 2SD756A..
2SC1260	Si-NPN	UHF-A/Dr, 45V, 0,03A, 0,25W, 2GHz	5g	Nec	BFR37, BFW30, BFX73, 2SC2570
2SC1261(F,S)	Si-NPN	UHF, LN, 20V, 0,03A, 0,3W, 2,5GHz	51r	Fui	BFQ59, BFR34, BFT97, 2SC2672
2SC1262(F,S)	Si-NPN	UHF-Dr/Out, 45V, 0,3A, 1,7GHz	55r	Fui	BFQ68, 2SC1043, 2SC1249..1251
2SC1263(F,S)	Si-NPN	=2SC1262: 1,9GHz	55r	Fui	BFQ68, 2SC1043, 2SC1250..1251
2SC1264(F)	Si-NPN	UHF-A/Dr, 30V, 0,1A, 0,4W, 2GHz	51r	Fui	BFG34, BFT12
2SC1265	Si-NPN	Dual, 20V, 0,05A, 0,6W, 3GHz	-	Nec	-
2SC1266	Si-NPN	Sw, 100V, 1,5A, 150MHz, <63/210nS	2a$	Nec	(BD139, BD529, BD843, 2SC2275,..)
2SC1267	Si-NPN	UHF-A/Dr, 45V, 0,3A, 7W, 2,2GHz	55s	Nec	BFQ68, 2SC1043, 2SC1250..1251
2SC1268	Si-NPN	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC1269	Si-NPN	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC127	Si-NPN	HF-Pre/Mix//Osc., 20V, 25mA, 200MHz	2a$	Nec	BF240..241, BF254..255, BF594..595,..
2SC1270	Si-NPN	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC1271(A)	Si-NPN	UHF, 20V, 0,03A, 0,2W, 6GHz	51s	Nec	BFG91, BFQ57..58, BFQ74, 2SC3276
2SC1272	Si-NPN	UHF, 20V, 0,1A, 4GHz	51s	Nec	BFG96, BFP96, BFQ73, BFR96
2SC1273	Si-NPN	UHF, 20V, 0,1A, 4GHz	51s	Nec	BFG96, BFP96, BFQ73, BFR96
2SC1274	Si-NPN	Sw, 40V, 0,3A, 0,3W, <80/86nS	2a$	Nec	BSS10, BSX19..20, BSX26, 2N3261
2SC1275	Si-NPN	UHF, LN, 30V, 25mA, 2GHz	5g	Nec	BF630, BFR15, BFS55, BFW99
2SC1276	Si-NPN	Sw, 40V, 0,1A, 0,2W, <20/40nS	7c	Nec	BSV91..92, BSX92..93, 2N2368..69(A),..
2SC1277	Si-NPN	GenP, 60V, 0,5A, 0,25W, 60MHz	7c	Nec	BC337A, BC637, 2SC3939, 2SD1226..
2SC1278	Si-NPN	Nix, 150V, 0,05A, 0,25W, 150MHz	7c	Nec	BF297..299, BF422, 2SC2375, 2SD2030,..
2SC1279(S)	Si-NPN	=2SC1278: 180V	7c	Nec	BF297..299, BF422, 2SC3248, 2SD2031,..
2SC128	Ge-NPN	Sw, 30V, 0,2A, 0,15W, 7MHz, <320/1300nS	2a	Mat	ASY28..29, ASY73..75
2SC1280(S)	Si-NPN-Darl	GenP, 15V, 0,3A, 0,25W, B>5000	7c	Nec	BCS17, BC617, MPSA13..14, 2SC4009..
2SC1280A(AS)	Si-NPN-Darl	=2SC1280: 40V, B>12000	7c	-	BCS17, BC617, MPSA25..26, 2SC4009..
2SC1281	Si-NPN	GenP, 20V, 0,02A, 0,3W, 120MHz	2a	Oki	BC168, BC183, BC238, BC548, 2SC1890+
2SC1282	Si-NPN	=2SC1282: 70V	2a	Oki	BC174, BC546, 2SC1890(A), 2SC2240..
2SC1283	Si-NPN	=2SC1281: 110V	2a	Oki	2SC1775A, 2SC1890A, 2SC2240, 2SC2363..
2SC1284	Si-NPN	UHF, 30V, 0,05A, 700MHz	7c	Sanyo	BF377..378, BF689K, BF763, 2N2857..
2SC1285	Si-NPN	GenP, 40V, 0,1A, 0,2W, 140MHz	7c	Sanyo	BC167, BC183, BC237, BC547, 2SD767..
2SC1286	Si-NPN	TV-IF, 25V, 0,05A, 400MHz	7c	Sanyo	BF198..199, BF224..225, BF310..311,..
2SC1287	Si-NPN	-		Sanyo	-
2SC1288	Si-NPN	Fast-Sw, 7V, 0,06A, 0,2W, 4,5GHz	24f	Oki	-

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2SC129	Ge-NPN	Sw,25V,0,2A,0,15W,10MHz,<265/1300nS	2a	Mat	ASY28..29,ASY73..75
2SC1290	Si-NPN	UHF-A,40V,0,2A,0,75W,1,5GHz	2a$	Oki	BFR36,2SC1199,2SC1252
2SC1292	Si-NPN	Sw,Pow,300/300V,2,5A,80W	23a$	Mitsubishi	BU126,BUW71,TIPS1..54,2SD632..
2SC1293	Si-NPN	HF,25V,0,05A,400MHz	7c	Say,Mic	BF198..199,BF224..225,BF310..311,..
2SC1294	Si-NPN	-		Sanyo	-
2SC1295	Si-NPN	TV-HD,1000/350V,2A,40W	23a$	Sanyo	BU204..206,2SC1132,2SD1097..1098..
2SC1296	Si-NPN	TV-HD,1300/400V,5A,50W	23a$	Sanyo	BU207..209,2SC2928,2SD350,2SD820..
2SC1297	Si-NPN	VHF-Pow,50V,3,5A,Pq=26W(175MHz)	55s	Nec	MRF314A..31SA,2SC2888
2SC1298	Si-NPN	VHF-Pow,50V,5A,Pq=37W(175MHz)	55s	Nec	BLW25,BLY94,2N5643,2SC2889
2SC1299(F)	Si-NPN	Sw,Pow,300/200V,30A,200W,25MHz	68a$	Fui	2SC1401,2SC1873,2SD542..543,2SD643,..
2SC13	Ge-NPN	AF,Sw,18V,0,04A,0,065W,>3,5MHz	2a	Tos	AC127,ASY28..29
2SC130	Si-NPN	HF/Sw-Pow,60V,1A,20W,160MHz	2a$	Fui	(BD137,BD228,2SC1398,2SC3252,..)
2SC1300(F)	Si-NPN	Sw,Pow,500V,30A,200W,20MHz	68a$	Fui	2SC1874,2SC2220,2SC2442,2SC2444..
2SC1301	Si-NPN	=2SC1301:250/200V	68a$	Fui	2SC1873,2SC2249,2SC2445,2SD643..
2SC1302	Si-NPN	=2SC1301:400/400V	68a$	Fui	2SC1401,2SC1470,2SC2250,2SD542..43,..
2SC1303(Z)	Si-NPN	VHF-Dr/Out,40V,0,3A,Pq=0,6W(175MHz)	2a$	Mat	BFX55,MRF207,MRF607
2SC1304	Si-NPN	AF-Pow,300/300V,0,5A,20W,7MHz	22a$	Hit	2N3739,2SC782,2SC1929,2SC2354..
2SC1305	Si-NPN	-		Nec	-
2SC1306	Si-NPN	HF-Pow,65V,3A(ss),Pq=5,5W(50MHz)	17j$	Nec	-
2SC1307	Si-NPN	HF-Pow,70V,8A(ss),Pq=15W(50MHz)	17j$	Nec	-
2SC1308	Si-NPN	TV-HD,1500/400V,7A,50W	23a$	Sanyo	BU508(A),2SC3027..28,2SD822,2SD1016
2SC1309	Si-NPN	TV-VD,1200/500V,5A,80W	23a$	Mitsubishi	2SC1413,2SD1099,2SD1103
2SC131	Si-NPN	Sw,40V,0,3A,0,35W,350MHz,-/40nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1310	Si-NPN	GenP,LN,50V,0,2A,0,3W,200MHz	41c	Mit	BC414,BCS50,2SC2240,2SC2674..75..
2SC1311	Si-NPN	=2SC1310:AM/FM	41c	Mit	BF240..241,BF254..255,BF594..595,..
2SC1312	Si-NPN	GenP,LN,35V,0,1A,0,2W,150MHz	7b	Mit	BC169,BC184,BC239,BC549,2SC1890+
2SC1313	Si-NPN	=2SC1312:50V	7b	Mit	BC184,BC414,BCS50,2SC2240..
2SC1314(A)	Si-NPN	VHF-Pow,40V,5A,Pq=34W(175MHz)	55r	Mit	BLW20,BLW31,2N6084
2SC1315	Si-NPN	VHF-Dr/Out,35V,0,5A,Pq=0,5W(150MHz)	2a	Mit	BFR98,BLW16,BLY61,MRF225..
2SC1316	Si-NPN	Sw,Pow,750/750V,2A,23W,8,5MHz	22a$	Son	BUV36(A),BUX84..85,2SC3149,2SC3352
2SC1317	Si-NPN	GenP,30V,0,5A,0,625W,200MHz	7c	Mat,Mic	BC337..338,BC635,BC637,2SC3377..
2SC1318	Si-NPN	=2SC1317:60V	7c	Mat	BC337A,BC637,BC639,2SD667..
2SC1318A	Si-NPN	=2SC1351:80V	7c	-	BC639,2SD667,2SD1226,2SD1768..
2SC1319	Si-NPN	HF/AF,AGC,40V,25mA,600MHz	7c	Nec	BF198,BF225,BF310,BF596,2SC2215+
2SC132	Si-NPN	Sw,20V,0,3A,0,35W,350MHz,-/40nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1320	Si-NPN	HF/AF,50V,30mA,850MHz	7c	Nec	BF199,BF224,BF311,2SC1855..S6..
2SC1321	Si-NPN	UHF,30V,10mA,900MHz	35a	Nec	BFS17,2SC3005,2SC3016,2SC3161
2SC1321-Q2	Si-NPN	-	35	Mot,Nec	→2SC1321
2SC1321-Q3	Si-NPN	-	35	Mot,Nec	→2SC1321
2SC1321-Q4	Si-NPN	-	35	Mot,Nec	→2SC1321
2SC1321-Q5	Si-NPN	-	35	Mot,Nec	→2SC1321
2SC1322	Si-NPN	Sw,Pow,250/200V,15A,100W,27MHz	23a$	Fujitsu	BUX13,BUX41,2SD552,2SD583,2SD3263..
2SC1323	Si-NPN	UHF-Dr/Out,30V,0,5A,5W,1300MHz	51r	Mit	BLX66,MRF627..628,2N6256
2SC1324	Si-NPN	UHF-A/Dr,35V,0,15A,0,8W,1,7GHz	5g	Mit	BFR36,BFW16,2SC1068
2SC1325(A)	Si-NPN	CTV-HD,1500/600V,6A,80W	23a$	NEC	BU208(A),BU508(A),2SC2928,2SD954,..
2SC1326(Z)	Si-NPN	VHF-Dr/Out,55V,0,4A,Pq>1W(400MHz)	2a$	Mat	BFS23,BFW47,BLY34,2N3553,2N5160
2SC1327	Si-NPN	GenP,LN,35V,0,05A,0,15W,250MHz	7c	Mat,Mic	BC169,BC184,BC239,BC549,2SC2675+
2SC1328	Si-NPN	=2SC1327:55V	7c	Mat	BC414,BCS50,2SC2240,2SC2390..
2SC1329	Si-NPN	FM-Pow,50V,8A,Pq=32W(70MHz)	55s	Nec	2SC2313
2SC133	Si-NPN	Sw,20V,0,3A,0,35W,350MHz,-/40nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1330	Si-NPN	GenP,50V,0,1A,0,4W,250MHz	7co	Nec,Mic	BC167,BC182,BC237,BC547,2SD767..
2SC1331	Si-NPN	IF,UHF,20V,0,02A,750MHz	5g	Nec	BF377..378,BF689,BF763,2N2857..
2SC1332	Si-NPN	-		Nec	-
2SC1333	Si-NPN	UHF-Dr/Out,45V,1A,10W,1200MHz	55s	Nec	BLW33..34,2N4430,2SC3140
2SC1334	Si-NPN	UHF-Dr/Out,50V,1A,11,6W,1200MHz	55s	Nec	BLW98,BLX98,2N4431,2SC3141
2SC1335	Si-NPN	GenP,LN,30V,0,1A,0,2W,230MHz	9b	Hitachi	BC169,BC184,BC239,BC549,2SC2675+
2SC1336	Si-NPN	UHF,LN,20V,0,03A,0,25W,4,5GHz	51s	Nec	BFQ71,BFQ85,BFR14,2SC1119
2SC1337(A)	Si-NPN	UHF-Pow,35V,2A,Pq=8,5W(485MHz)	55r*	Mit	BLW14,BLW44,2N5946
2SC1338(A)	Si-NPN	UHF-Pow,35V,3A,Pq=16W(485MHz)	55r*	Mit	BLW15,BLX69
2SC1339	Si-NPN	UHF-Pow,35V,5A,Pq=28W(485MHz)	55r*	Mit	BLW15,BLX69
2SC134	Si-NPN	Sw,40V,0,3A,0,35W,350MHz,-/125nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1340	Si-NPN	UHF-Dr/Out,35V,1A,5W,1GHz	55r	Mit	BLU97,BLW43,BLW80,BLX68,BLY53
2SC1341	Si-NPN	-		Mit	-
2SC1342	Si-NPN	FM-Preamp/Mix/Osc,320MHz	9b,7c	Hit	BF240..241,BF254..255,BF594..595,..

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2SC1343	Si-NPN	150V,10A,100W,14MHz	-		-
2SC1343(H)	Si-NPN	AF,Sw-Pow,150V,10A,100W,14MHz	23a$	Hit	BD245D,2SD551,2SD733,2SD1047..
2SC1344	Si-NPN	AF,LN,30V,0,1A,0,2W,230MHz	9b,7c	Hit	BC169,BC184,BC239,BC549,2SC2675+
2SC1345	Si-NPN	55V,0.1A,0.1W,230MHz	-		-
2SC1345(K)	Si-NPN	=2SC1344:55V	9b,7c	Hit	BC414,BC550,2SC2240,2SC2459..
2SC1346	Si-NPN	=2SC1317:0,6W	7co	Mat,Mic	→2SC1317
2SC1347	Si-NPN	=2SC1318:0,6W	7co	Mat,Mic	→2SC1318
2SC1348(-1..-3)	Si-NPN	TV-HD,1000..1200V,4A,125W,5MHz	23a$	Sony	(BU207..209,BU508,2SC2928,2SD954..)
2SC1349(F)	Si-NPN	Fast-Sw,20V,0,2A,0,2W,-/15nS	2a$	Fui	BSS11,BSX19..20,2N2369..69(A)..
2SC135	Si-NPN	Sw,20V,0,3A,0,3SW,350MHz,-/125nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1350	Si-NPN	Sw,25V,0,3A,0,3W,<-/60nS	2a$	Fui	BSS11,BSX19..20,2N2369..69(A)..
2SC1351	Si-NPN	Sw,80V,1A,0,8W,<50/85nS	2a	Fui	BSV95,2N3735,2SC1069
2SC1352	Si-NPN	Sw,25V,0,8A,0,6W,<15/20nS	2a$	Fui	BSS28..29,BSV69,BSX12,2N3426..
2SC1353	Si-NPN	Sw,90V,0,7A,0,65W,45/95nS	2a	Fui	BSW39,2SC1069
2SC1354(Z)	Si-NPN	VHF-Pow,55V,5A,Pq=37W(175MHz)	60c*	Mat	-
2SC1355(F)	Si-NPN	UHF-Dr/Out,40V,0,7A,Pq=2W(700MHz)	55r	Fui	BLU99
2SC1356(F)	Si-NPN	UHF-Dr/Out,40V,1A,Pq=6W(700MHz)	55r	Fui	-
2SC1357	Si-NPN	-		Nec	-
2SC1358(A)	Si-NPN	TV-HD(90°),1400/500V,4,5A,50W	23a$	NEC	BU208..209,BU508(A),2SD783,2SD954..
2SC1359	Si-NPN	GenP,30V,0,03A,0,4W,250MHz	7c	Mat,Mic	BC237,BC548,BF240..241,BF254..255..
2SC136	Si-NPN	Sw,80V,0,3A,0,35W,350MHz,-/125nS	2a$	Fui	2N4014
2SC1360	Si-NPN	50V,0.05A,1W,>300MHz	-		-
2SC1360(A)	Si-NPN	TV-IF,50(A=60)V,0,05A,1W,>300MHz	7c(9mm)	Mat	BF370,BF920..921(S),BF959
2SC1361	Si-NPN	GenP,LN,25V,0,2A,0,25W,140MHz	7c	Son	BC169,BC184,BC239,BC549,2SC2275+
2SC1362	Si-NPN	=2SC1361:50V	7c	Son	BC414,BC550,2SC2240,2SC2459..
2SC1363	Si-NPN	GenP,25V,0,2A,0,25W,140MHz	7c	Son	BC168,BC183,BC238,BC548,2SD767..
2SC1364	Si-NPN	=2SC1363:50V	7c	Son	BC167,BC182,BC237,BC547,2SD767..
2SC1365	Si-NPN	UHF-A/Dr,45V,0,3A,0,8W,1,7GHz	2a$	Nec	2SC1199,2SC1252..1253,2SC2852
2SC1366	Si-NPN	=2SC1365:2GHz	2a$	Nec	2SC1253,2SC2852
2SC1367(A)	Si-NPN	TV-VD,1000V,1A,50W,6MHz	23a$	Hitachi	BU204..206,2SC1101,2SC1167,2SD1095..
2SC1368	Si-NPN	AF,Sw-Pow,25V,1,5A,8W,180MHz	14h$	Hit	BD135,BD226,BD375,2SD1380..
2SC1369..1371	Si-NPN	-		Shi	-
2SC137	Si-NPN	Sw,25V,0,3A,0,35W,350MHz,-/40nS	2a$	Fui	BSS10,BSX19..20,BSX26,2N3261..
2SC1372	Si-NPN	GenP,30V,0,2A,0,2W,250MHz	7c	Fui	BC168,BC183,BC238,BC548,2SD767..
2SC1373	Si-NPN	GenP,25V,0,1A,0,3W,<100/325nS	2a$	Hit	BC238,BC548,BSY62..63,2N706A..
2SC1374(H)	Si-NPN	Fast-Sw,25V,0,1A,0,3W,<13/16nS	2a$	Hit	BSV89..92,BSX92..93,2N2368..69(A),..
2SC1375(H)	Si-NPN	Fast-Sw,25V,0,1A,0,3W,<45/60nS	2a$	Hit	BSV89..92,BSX92..93,2N2368..69(A),..
2SC1376(H)	Si-NPN	Fast-Sw,40V,0,5A,0,3W,<25/40nS	2a$	Hit	BSS10,BSX26,BSX39,2N3261
2SC1377	Si-NPN	AM/SSB-Pow,90V,6A,Pq>8W(27MHz)	17j$	Tos	2SC1307,2SC1944,2SC1969,2SC2098
2SC1378	Si-NPN	VHF-Pow,40V,4A,Pq=25W(175MHz)	55r*	Tos	BLY89,MRF209,2N5591,2N6082
2SC1379	Si-NPN	VHF-Pow,40V,7A,Pq=40W(175MHz)	60c*	Tos	-
2SC138(A)	Si-NPN	FM/VHF-A/Tr,60V,0,5A,0,8W,400MHz	5g	Nec	BFS23,BFX55,BLY34,2SC2852
2SC1380	Si-NPN	GenP,55V,0,1A,0,2W,80MHz	2a$	Tos	BC167,BC182,BC237,BC547,2SD767..
2SC1380A	Si-NPN	=2SC1380:ra	2a$	-	BC414,BC550,2SC2240,2SC2459..
2SC1381	Si-NPN	AF,Sw-Pow,100V,1A,5W,50MHz	14h$	Tos	BD139,BD230,BD379,2SC2690..
2SC1382	Si-NPN	AF,Sw-Pow,80V,0,75A,5W,100MHz	14h$	Tos	BD139,BD230,BD379,2SC2690..
2SC1383(NC)	Si-NPN	GenP,30V,1A,1W,200MHz	7c(9mm)	Mat	2SC2236,2SD863,2SD1207,2SD1331..
2SC1384	Si-NPN	60V,1A,1W,200MHz	-		-
2SC1384(NC)	Si-NPN	=2SC1383:60V	7c(9mm)	Mat	2SC3328,2SC4145,2SD863,2SD1207..
2SC1385(H)	Si-NPN	Sw,60V,0,5A,0,8W,<40/60nS	2a$	Hit	BSS27,BSV77,2N5189,2SC1072..
2SC1386(H)	Si-NPN	Sw,70V,1A,0,8W,<30/55nS	2a$	Hit	BSS27,BSV95,2N3735,2SC1069..
2SC1387	Si-NPN	UHF,CATV,25V,0,15A,0,5W,1,6GHz	2a	Fui	BFR36,BFW16,2SC1068,2SC1324
2SC1388(F)	Si-NPN	Sw,100V,1A,0,8W,<50/110nS	2a$	Fui	2SC1069
2SC1389	Si-NPN	-		Fui	-
2SC139	Si-NPN	=2SC138	5g	-	BFS23,BFX55,BLY34,2SC2852
2SC1390	Si-NPN	GenP,LN,20V,0,05A,0,2W,230MHz	7c	Hit	BC169,BC184,BC239,BC549,2SC2390+
2SC1391	Si-NPN	Vid-Pow,300V,0,1A,6,5W,25MHz	22a$	Hit	2SC1505..1507,2SC1749,2SC1819..
2SC1392	Si-NPN	-		Nec	-
2SC1393	Si-NPN	VHF-Pre,LN,30V,0,02A,700MHz	7f	Nec	BF225,BF310,BF314,2SC1856..
2SC1394	Si-NPN	VHF-Mix,30V,0,02A,700MHz	7f	Nec	BF224,BF310,BF314,2SC3136..
2SC1395	Si-NPN	VHF-Osc,30V,0,02A,>600MHz	7c	Nec	BF377..378,BF689K,BF763,2N2857..
2SC1396	Si-NPN	=2SC1395:>800MHz	7c	Nec	BF377..378,BF689K,BF763,2N2857..
2SC1397	Si-NPN	-		Nec	-
2SC1398	Si-NPN	70V,2A,15W	-		-

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2SC1398(A)	Si-NPN	AF,Sw-Pow,70V,2A,15W,120MHz	17j$	Mat	2SC2528,2SC3252
2SC1399	Si-NPN	GenP,100V,0,05A,0,25W,100MHz	7c	Nec	2SC1890A,2SC2363,2SC3245,2SD756(A)..
2SC14	Ge-NPN	=2SC13: >11MHz	2a	Tos	AC127,ASY28..29
2SC140	Si-NPN	GenP,60V,1A,1,7W,150MHz	2a$	Son	BC140..141,BCX40,2N1990,2N2102..
2SC1400	Si-NPN	=2SC1399:ra	7c	Nec	2SC1775A,2SC2088,2SC2240,2SC2459..
2SC1401	Si-NPN	Sw,Pow,400/350V,30A,200W,20MHz	68a$	Fui	2SC1302,2SC1470,2SC2250,2SD542..543
2SC1402	Si-NPN	AF,Sw-Pow,140V,8A,70W,10MHz	23a$	Sak	BD245D,2N3442,2SD551,2SD1047..
2SC1403	Si-NPN	=2SC1402: 160V	23a$	Sak	BD245D,2N3442,2SD551,2SD1047..
2SC1403A	Si-NPN	=2SC1402: 180V	23a$	Sak	BD245E,BDW16,2SC2261..62,2SD751..
2SC1404	Si-NPN	UHF-Pow,36V,3,5A,Pq=18W(470MHz)	55r	Mat	BLX69,2SC1338
2SC1405(Z)	Si-NPN	VHF-Dr/Out,36V,0,75A,Pq=3,5W(175MHz)	51r	Mat	BLW17,2SC1011
2SC1406	Si-NPN	GenP,30V,1A,1W,200MHz	7co	Mat	BC337..338,BC635,BC637,2SD1225..
2SC1407	Si-NPN	=2SC1406:60V	7co	Mat	BC337A,BC637,BC639,2SD667..
2SC1408	Si-NPN	-		Sanyo	-
2SC1409(A)	Si-NPN	AF-Pow,200/120(A=140)V,2A,12,5W,20MHz	17j$	Hit	BD239F,2SC2660,2SD760,2SD1138..
2SC141	Si-NPN	HF/Sw,20V,0,2A,0,36W,450MHz	2a$	Oki	BSS11,2N2368..69(A),2SC2901,2SC3732
2SC1410(A)	Si-NPN	AF-Pow,200V,2A,12,5W,20MHz	17j$	Hit	BD239F,2SC2660,2SD760,2SD1138..
2SC1411	Si-NPN	Chopper,6V,0,05A,0,2W	2a$	Fui	-
2SC1412	Si-NPN	UHF-A/Dr,45V,0,15A,0,6W,1,5GHz	2a$	Fui	BFR36,BFW16,2SC1068,2SC1324
2SC1413(H)	Si-NPN	TV-HD,1200/500V,5A,50W,4MHz	23a$	Hitachi	BU207..209,BU508,2SD1099,2SD1103,..
2SC1413A	Si-NPN	1200V,5A,50W	-		-
2SC1413A(AH)	Si-NPN	=2SC1413: 1500/500V	23a$	-	BU208..209,BU508,2SC2928,2SD954..
2SC1414(F)	Si-NPN	UHF-Pow,40V,2A,Pq=10W(700MHz)	55r	Fui	2SC1087
2SC1415(F)	Si-NPN	UHF-Pow,40V,3A,Pq=16W(700MHz)	55r	Fui	2SC1087
2SC1416(A)	Si-NPN	GenP,LN,55V,0,05A,0,2W,100MHz	2a	Tos	BC414,BC550,2SC2240,2SC2390..
2SC1417	Si-NPN	HF,20V,0,03A,300MHz	9b	Hitachi	BF240..241,BF254..255,BF594..595,..
2SC1418	Si-NPN	AF,Sw-Pow,50V,2A,20W,5MHz	17j$	Hit	BD239,2SC1398,2SC2528,2SC3252..
2SC1419	Si-NPN	=2SC1418	17j$	Hit	BD239,2SC1398,2SC2528,2SC3252..
2SC142	Si-NPN	HF/Sw,30V,0,2A,0,36W,28/42nS	2a$	Oki	BSS11,2N2368..69(A),2SC2901,2SC3732
2SC1420	Si-NPN	UHF,15V,0,07A,0,3W,6GHz	51r	Fui	2SC2876,2SC3603
2SC1421	Si-NPN	UHF,15V,0,03A,0,25W,5,5GHz	51r	Fui	BFG91,BFP91,BFQ57..58,BFQ74
2SC1422(F)	Si-NPN	UHF,15V,0,04A,0,25W,5,5GHz	51r	Fui	BFG91,BFP91,BFQ57..58,BFQ74
2SC1423	Si-NPN	UHF,15V,0,03A,0,25W,7GHz	51r	Fui	BFG65,BFQ66,2SC3062,2SC3276
2SC1424	Si-NPN	VHF/UHF-Pre,LN,2GHz	5g	Nec	BF377..378,BFR37,BFS55,BFW30..
2SC1425	Si-NPN	UHF-Dr/Out,45V,1A,Pq=3W(1GHz)	55s	Nec	2N4430
2SC1426	Si-NPN	UHF-A/Dr,35V,0,2A,2,7GHz	5g	Nec	-
2SC1427	Si-NPN	UHF,30V,10mA,1GHz	35a	Nec	BFS17,2SC3005,2SC3016,2SC3161
2SC1428	Si-NPN	GenP,50V,0,05A,250MHz	35a	NEC	BC846..847,BCW71..72,BCW81,2SC3323
2SC1429-..	Si-NPN	AF/HF/Sw,12..16V,2A,80MHz	13g$	Sony	(BC365,BD505,BD515,2SD1177..78,..)
2SC143	Si-NPN	HF/Sw,40V,0,2A,0,36W,28/42nS	2a$	Oki	BSS11,2N2368..69(A),2SC2901,2SC3732
2SC1430-1	Si-NPN	AF,Sw,110/110V,1,5A,0,5W,50MHz	2a$	Son	BCX40,BSS42..43,BSW67..68,BSX47
2SC1430-2	Si-NPN	=2SC1430-1: 140/140V	2a$	-	BSS43,BSW68,2SC1860
2SC1431	Si-NPN	110V,2A,23W,80MHz	-		-
2SC1431-1	Si-NPN	AF,Sw-Pow,110/110V,2A,23W,80MHz	22a$	Son	2SC2528..2529,2SD759
2SC1431-2	Si-NPN	=2SC1431-1: 140/140V	22a$	-	2SC2529,2SD759
2SC1432	Si-NPN-Darl	GenP,30V,0,3A,0,3W,B=40000	7c	Njr	BCS17,MPSA13..14,2SC4009,2SC40174..
2SC1433	Si-NPN	Sw,Pow,600/400V,5A,50W,2/11,5µS	23a$	Tos	BUW25,BUX82,2SC2962,2SD640..
2SC1434	Si-NPN	Sw,Pow,600/440V,15A,150W,2/17,5µS	23a$	Tos	BUS13,BUW45..46,BUX48,2SD641..
2SC1435	Si-NPN	Sw,Pow,600/400V,40A,300W,11/11,5µS	68a$	Tos	2SD642
2SC1436	Si-NPN	Sw,Pow,230/230V,15A,100W,10MHz	23a$	Sanken	BUW50..52,BUX41,BUX70,2SD583..
2SC1437	Si-NPN	=2SC1436: 50A,200W	68a$	Sak	2SC2147,2SC2159,2SC2942
2SC1438	Si-NPN	Vid,150/120V,0,05A,0,5W,130MHz	7c	Fui	BF297..299,BF422,2SC2375,2SD2030,..
2SC1439	Si-NPN	=2SC1438: 150/150V	7c	Fui	BF297..299,BF422,2SC2363,2SD2030,..
2SC144(A)	Si-NPN	HF/Sw,50(A=60)V,0,2A,0,36W,28/47nS	2a$	Oki	2SC1834
2SC1440	Si-NPN	Sw,Pow,150/150V,15A,100W,10MHz	23a$	Sanken	BD745E,BUX41,2SC1584,2SD552..
2SC1441	Si-NPN	=2SC1440: 200V	23a$	Sak	BDW16,BUX41,2SC1585,2SD552..
2SC1442	Si-NPN	=2SC1440: 50A,200W	68a$	Sak	2SC1437,2SC2147,2SC2159,2SC2942
2SC1443	Si-NPN	=2SC1440: 200V,50A,200W	68a$	Sak	2SC1437,2SC2147,2SC2159,2SC2942
2SC1444	Si-NPN	AF,Sw-Pow,80V,6A,40W,10MHz	22a$	Sak	BD243B,BD543B,BD799,2N5427..28..
2SC1445	Si-N	=2SC1444: 100V	22a$	Sak	BD243C,BD543C,BD801,2N5429..30,+
2SC1446	Si-NPN	AF/Vid-Pow,300V,0,1A,10W(Tc=70°)	17j$	Mat	2SC1505..1507,2SC1755..1757,2SC1905,..
2SC1447	Si-NPN	AF/Vid-Pow,300/300V,0,15A,20W,80MHz	17j$	Tos	2SC1505..1507,2SC1755..1757,2SC1905,..
2SC1448	Si-NPN	150V,1.5A,25W,3MHz	-		-
2SC1448(A)	Si-NPN	AF,Sw-Pow,150/150V,1,5A,25W,5(A=7)MHz	17j$	Tos	BD239D,2SC2073,2SD608(A),2SD1138..

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2SC1449	Si-NPN	AF-Pow,40V,2A,5W,60MHz	14h$	Nec	BD375,2SD1380,2SD882,2SD1818..
2SC145	Si-NPN	HF/Sw,30V,0,2A,0,36W,500MHz	2a$	Oki	BSS11,2N2368..69(A),2SC2901,2SC3732
2SC1450	Si-NPN	150V,0.4A,20W	-		-
2SC1450(S)	Si-NPN	AF,Sw-Pow,150/150V,0,4A,20W(Tc=80°)	22a$	Mat	BD239D,2SC2073,2SD608,2SD1138..
2SC1451	Si-NPN	Sw,Vid,150/120V,0,05A,0,7W,130MHz	2a$o	Fui	BF257..258,2N5058..59,2SC3467..68..
2SC1452	Si-NPN	=2SC1451:150/150V	2a$o	Fui	BF257..258,2N5058..59,2SC3467..68..
2SC1453	Si-NPN	GenP,55V,0,1A,0,2W,150MHz	2a	Tos	BC167,BC182,BC237,BC547,2SD767..
2SC1454	Si-NPN	Sw,Pow,300/250V,4A,50W,10MHz,-/7,2µS	23a$	Sanken	BU606..608,BUW71,2SC2624,2SD632..
2SC1456	Si-NPN	Vid-Pow,300/300V,0,2A,15W,80MHz	22a$	Nec	2SC1505..1507,2SC1755..1757,2SC1905
2SC1457	Si-NPN	UHF-A/Dr,LN,35V,0,15A,0,8W,2,7GHz	5g	Nec	BFR95
2SC1458	Si-NPN	UHF,20V,0,05A,0,3W,3GHz	51s	Nec	BFQ72,2SC2844,2SC3302
2SC1459	Si-NPN	=2SC1420	51r	Fui	→2SC1420
2SC146(A)	Si-NPN	HF/Sw,50(A=60)V,0,2A,0,36W,500MHz	2a$	Oki	2SC1834
2SC1460	Si-NPN	=2SC1421	51r	Fui	→2SC1421
2SC1461	Si-NPN	=2SC1422	51r	Fui	→2SC1422
2SC1462	Si-NPN	=2SC1423	51r	Fui	→2SC1423
2SC1463	Si-NPN	Sw,Pow,450/400V,4A,75W,25MHz,-/<8µS	23a$	Fujitsu	BUW71,BUX45,2SC2624,2SC3083..
2SC1464	Si-NPN	VHF-Dr/Out,50V,0,5A,Pq=1,2W(175MHz)	2a	Fui	BFR98,BFS23,BLW16,BLY34,BLY61
2SC1465	Si-NPN	UHF-Dr/Out,50V,0,5A,Pq=1,8W(700MHz)	51r	Fui	-
2SC1466	Si-NPN	Sw,Pow,450/360V,3A,30W,10MHz	22a$	Shi	BUT93,BUY63..64,TIP75B,2SC2929..
2SC1467	Si-NPN	=2SC1466:500/400V	22a$	Shi	BUT93,BUY63..64,TIP75C,2SC2826..
2SC1468	Si-NPN	Sw,Pow,450/360V,10A,100W,10MHz	23a$	Shidengen	BUW24..26,BUW34..36,2SC4138..
2SC1469(A)	Si-NPN	=2SC1468:500/400V	23a$	Shi	BUW25..26,BUW34..36,2SC4138..
2SC147	Si-NPN	GenP,30V,1A,0,75W,120MHz	2a$	Son	BC140..141,BCX40,2N1990,2N2102..
2SC1470	Si-NPN	Sw,Pow,450/360V,30A,200W,10MHz	68a$	Shi	2SC1300,2SC1874,2SC2220,2SC2444..
2SC1471(A)	Si-NPN	=2SC1470:500/400V	68a$	Shi	2SC1300,2SC1874,2SC2220,2SC2444..
2SC1472(K)	Si-NPN-Darl	GenP,40V,0,3A,0,5W,>50MHz,B>2000	9b,7c	Hit	BC517,BC617,BC875,MPSA25..29..
2SC1473(NC)	Si-NPN	Vid,250/200V,0,07A,0,75W,80MHz	7c	Mat	BF298..299,BF422,2SC3468..69..
2SC1473A	Si-NPN	=2SC1473:300/300V	7c	Mat	BF299,BF420,BFR89,2SC3468..
2SC1474-	Si-NPN	GenP,20V,2A,0,75W,80MHz	7c(9mm)	Son	2SD787..788,2SD1100,2SD1146,2SD1207..
2SC1474-4	Si-NPN	20V,2A,0.75W,80MHz	-		-
2SC1475-	Si-NPN	GenP,100V,1A,0,75W,80MHz	7c(9mm)	Son	2SC3228,2SD667,2SD1292,2SD1812..
2SC1476	Si-NPN	UHF-Pow,38V,5A,Pq=28W(470MHz)	55r	Tos	2SC1339
2SC1477	Si-NPN	Sw,Pow,230V,9A,80W,10MHz	23a$	Sanken	BUX17(A..C),BUY18,TIP160..162..
2SC1478	Si-NPN	GenP,35V,0,05A,0,15W,150MHz	?2b	Mat	BC168,BC183,BC238,BC548,2SC1890+
2SC1478A	Si-NPN	=2SC1478:55V	?2b	-	BC167,BC182,BC237,BC547,2SC1890+
2SC1479	Si-NPN	VHF-Dr/Out,36V,0,5A,Pq=1,2W(175MHz)	2a$	Fui	BFR98,BFS51,BFQ42,BLW16,BLY61
2SC1480	Si-NPN	UHF-Dr/Out,36V,0,5A,Pq=2,4W(470MHz)	55r	Fui	BLW79,BLX67,BLY38,2N5945
2SC1481	Si-NPN	UHF-Pow,36V,1A,Pq=5W(470MHz)	55r	Fui	BLW43,BLW80
2SC1482	Si-NPN	UHF-Pow,36V,2A,Pq=8,5W(470MHz)	55r	Fui	BLW44,2N5946,2SC1337
2SC1482A	Si-NPN	=2SC1482:2,5A,Pq=15W(470MHz)	55r	-	BLW15,BLX69,2SC1338
2SC1483(F)	Si-NPN	UHF,LN,20V,0,04A,3GHz	51r	Fui	BFQ59,BFQ70,BFR34,BFT97
2SC1484	Si-NPN	UHF-Dr/Out,45V,0,3A,5W,2GHz	55r	Fui	BFR65,2SC1043,2SC1250..1251
2SC1485	Si-NPN	Sw,Vid,250/250V,0,125A,0,35W	2a$	Fui	BF298..299,BF422A,2SC3468..69..
2SC1486	Si-NPN	=2N5944	-	Mot	→2N5944
2SC1487	Si-NPN	=2N5945	-	Mot	→2N5945
2SC1488	Si-NPN	=2N5946	-	Mot	→2N5946
2SC1489	Si-NPN	=2N6136	-	Mot	→2N6136
2SC149	Si-NPN	VHF/Sw,120V,0,3A,0,8W,160MHz	2a$	Nec	BC300,2N1893(A),2SD413,2SD624
2SC1490	Si-NPN	=2N6080	-	Mot	→2N6080
2SC1491	Si-NPN	=2N6081	-	Mot	→2N6081
2SC1492	Si-NPN	=2N6082	-	Mot	→2N6082
2SC1493	Si-NPN	=2N6083	-	Mot	→2N6083
2SC1494	Si-NPN	=2N6084	-	Mot	→2N6084
2SC1495	Si-NPN	=2N6256	-	Mot	→2N6256
2SC1498	Si-NPN	UHF-Pow,36V,2,5A,45W	57s	Mot	BLU20/12;MRF641
2SC1499	Si-NPN	UHF-Pow,36V,6A,115W	57s	Mot	BLU30/12,MRF644
2SC15-0	Si-NPN	GenP,30V,0,05A,0,75W,150MHz	2a$	Son	BC183,BC238,BC548,2N2218..19..
2SC150(H)	Si-NPN	GenP,20V,0,1A,0,75W,100MHz	2a$	Hit	BC168,BC183,BC238,BC548,2N2218..
2SC1500	Si-NPN	UHF-Pow,36V,8A,115W	57s	Mot	BLU45/12,BLW82,MRF646
2SC1501	Si-NPN	Vid-Pow,300V,0,1A,10W,55MHz	14h$	Mat	BF417,BF459,2SC3417,2SC3503
2SC1502	Si-NPN	-		Tos	-
2SC1503	Si-NPN	VHF/UHF-Pow,50V,3A,Pq=13W(260MHz)	55r	Tos	BLW94,BLX94,MRF323,2SC1118
2SC1504	Si-NPN	Sw,Pow,400/300V,2A,40W,10MHz	22a$	Sak	BUX67C,2N3585,2N4240,2SC3055..

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2SC1505	Si-NPN	Vid-Pow,300V,0,2A,15W,80MHz	17j$	Nec	2SC1755..1757,2SC1905,2SC4714
2SC1506	Si-NPN	=2SC1505	17j$	Nec	2SC1755..1757,2SC1905,2SC4714
2SC1507	Si-NPN	=2SC1505	17j$	Nec	2SC1755..1757,2SC1905,2SC4714
2SC1508	Si-NPN	-		Mit	-
2SC1509	Si-NPN	80V,0.5A,1W,120MHz	-		-
2SC1509(NC,Z)	Si-NPN	GenP,80V,0,5A,1W,120MHz	7c(9mm)	Mat	2SC3939,2SC3328,2SD667,2SD1812..
2SC150T	Si-NPN	=2SC150:50V	2a$	-	BC167,BC182,BC237,BC547,2N2218..
2SC15-1	Si-NPN	=2SC15-0:60V	2a$	-	BC182,BC190,BC546,2N2218..19..
2SC151(H)	Si-NPN	GenP,40V,0,2A,0,75W,130MHz	2a$	Hit	BC167,BC182,BC237,BC547,2N2218..
2SC1510	Si-NPN	UHF-Pow,47V,1A,Pq=4,5W(770MHz)	55r	Mit	BLW98,BLX98,2N4431
2SC1511	Si-NPN	VHF/UHF-Pow,50V,3A,Pq=25W(275MHz)	57s*	Nec	MRF325..326
2SC1512	Si-NPN	VHF/UHF-Pow,50V,5A,Pq=37W(275MHz)	57s*	Nec	2N6439,2SC2796,2SC2895
2SC1513	Si-NPN	VHF/UHF-Dr/Out,40V,0,3A,1,8GHz	5g	Hit	2SC1199,2SC1252,2SC1365..1366
2SC1514	Si-NPN	Vid-Pow,300/300V,0,1A,80MHz	17j$	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC1515	Si-NPN	200V,0.05A,0.2W,110MHz	-		-
2SC1515(K)	Si-NPN	Vid,200/150V,0,05A,0,2W,110MHz	9b,7c	Hit	BF298..299,BF422,2SC3468..69..
2SC1516(K)	Si-NPN	AF,Sw-Pow,35V,1,5A,10W,110MHz	17j$	Hit	2SC1398,2SC2275,2SC2528,2SC3252
2SC1517	Si-NPN	AF,Sw-Pow,50V,1A,10W,150MHz	17j$	Hit	2SC1398,2SC2275,2SC2528,2SC3252
2SC1517A	Si-NPN	=2SC1517:80V	17j$	-	2SC1398,2SC2275,2SC2528,2SC3252
2SC1518(NC)	Si-NPN	DC-DCConv.,25V,1A,1W,150MHz	7c(9mm)	Mat	2SC2236,2SD863,2SD1207,2SD1331..
2SC1519	Si-NPN	Vid-Pow,250/250V,0,2A,10W,80MHz	13j$	NEC	(BF615,BF617,BF858..859,2SC1758,..)
2SC15-2	Si-NPN	=2SC15-0:90V	2a$	-	2SC1890(A),2SC2240,2SD755..756(A)..
2SC152(H)	Si-NPN	GenP,60V,0,2A,0,75W,160MHz	2a$	Hit	BC174,BC182,BC190,BC546,2N2218..
2SC1520	Si-NPN	300V,0.2A,12,5W	-		-
2SC1520-	Si-NPN	Vid-Pow,250..300V,0,2A,12,5W,80MHz	13j$	NEC	(BF617,BF859,BF758,MPSU10,..)
2SC1521	Si-NPN	=2SC1520	13j$	Nec	2SC1520
2SC1522	Si-NPN	=2SC1519:	?13j$	Nec	→2SC1519
2SC1523	Si-NPN	VHF/UHF-Dr/Out,40V,0,3A,2GHz	55r	Hit	BFQ41,MRF626,2N5944
2SC1524	Si-NPN	UHF-Pow,50V,1A,Pq=8W(700MHz)	55r	Fui	-
2SC1525	Si-NPN	UHF-Pow,50V,2A,Pq=13W(700MHz)	55r	Fui	2SC1087
2SC1526	Si-NPN	UHF-Pow,50V,3A,Pq=22W(700MHz)	55r	Fui	-
2SC1527	Si-NPN	-		Fui	-
2SC1528	Si-NPN	VHF-Pow,40V,2,5A,Pq=16W(175MHz)	25r	Mit	-
2SC1529	Si-NPN	UHF-A,30V,0,02A	5g	Mit	BF689,BFX62,BFX89,BFR37,BFW30..
2SC153	Si-NPN	GenP,120V,0,2A,0,75W,140MHz	2a$	Hit	2SC2240,2SC2459,2SC3245(A),2SC3248
2SC15-3	Si-NPN	=2SC15-0:120V	2a$	-	2SC1890A,2SC2240,2SD756(A)..
2SC1530	Si-NPN	UHF-Dr/Out,50V,0,35A,Pq=1,5W(1GHz)	55r	Mit	BFT99,2SC2956
2SC1531	Si-NPN	-		Tos	-
2SC1532	Si-NPN	Sw,Pow,300/200V,30A,200W,>5MHz	68a$	Tos	2SC1299,2SC1302,2SC1873,2SD643..
2SC1533	Si-NPN	UHF-Dr/Out,45V,0,5A,Pq=2,2W(700MHz)	55r	Fui	2SC1082
2SC1534	Si-NPN	UHF-Dr/Out,45V,1A,Pq=7W(700MHz)	55r	Fui	-
2SC1535	Si-NPN	UHF-Pow,45V,2A,Pq=12W(700MHz)	55r	Fui	2SC1087
2SC1536	Si-NPN	UHF-Pow,45V,4A,Pq=24W(700MHz)	55r	Fui	-
2SC1537	Si-NPN	GenP,50V,0,03A,0,15W,200MHz	9c	Rhm	BC167,BC182,BC237,BC547,2SC1890+
2SC1538	Si-NPN	=2SC1537:ra	9c	Rhm	BC184,BC414,BC550,2SC1775(A)..
2SC1539	Si-NPN	GenP,25V,0,03A,0,15W,200MHz	9c	Rhm	BC168,BC183,BC238,BC548,2SC1890+
2SC154(A..C,H)	Si-NPN	Vid,120..200V,0,1A,0,75W,150MHz	2a$	Hit	BF258..259,BF658..659,2N5058..59
2SC1540	Si-NPN	=2SC1539:ra	9c	Rhm	BC169,BC184,BC239,BC549,2SC1775+
2SC1541	Si-NPN	GenP,40V,0,15A,0,3W,250MHz	9c	Rhm	BC167,BC182,BC237,BC547,2SD767..
2SC1542	Si-NPN	=2SC1541:25V	9c	Rhm	BC168,BC183,BC238,BC548,2SD767..
2SC1543	Si-NPN	GenP,40V,0,02A,0,15W,<200/300nS	9c	Rhm	BC167,BC182,BC237,BC547,2N3904..
2SC1544	Si-NPN	=2SC1543:25V	9c	Rhm	BC168,BC183,BC238,BC548,2N3904..
2SC1545	Si-NPN-Darl	40V,0.3A,0.3W,B=1000	-		-
2SC1545(M)	Si-NPN-Darl	GenP,40V,0,3A,0,3W,250MHz,B=10000	9c	Rhm	BC517,BC617,BC875,MPSA25..29..
2SC1546	Si-NPN-Darl	=2SC1545:25V	9c	Rhm	BC517,BC617,BC875,MPSA13..14..
2SC1547	Si-NPN	UHF,30V,0,02A,900MHz	5g	Mat	BF377..378,BF689,BF763,2N2857..
2SC1548	Si-NPN	VHF/UHF-Pow,50V,5A,Pq=23W(260MHz)	55r	Tos	BLX95,2N6105
2SC1549	Si-NPN	AF/Vid,150V,0,05A,0,75W,130MHz	2a$o	Fui	BF297..299,BF422,2SC3245A,2SC3248..
2SC155	Si-NPN	Min,HF,20V,25mA,200MHz,a=35	?36b	Fui	BC122..123,BC146,(BF254..255,..)
2SC1550	Si-NPN	Vid-Pow,250/250V,0,1A,10W,100MHz	14h$	Mat	BF415,BF417,BF458..459,2SC3417..
2SC1551	Si-NPN	UHF,LN,20V,0,03A,0,2W,6,5GHz	51r	Tos	BFQ57..58,BFQ74,2SC3276
2SC1552	Si-NPN	UHF,LN,20V,0,03A,0,25W,4,5GHz	51r	Tos	BFQ71,BFQ85,BFR14,BFR91
2SC1553(A)	Si-NPN	UHF,LN,20V,0,03A,0,175W,4,5GHz	5g	Tos	BFQ22,BFT66..67
2SC1554	Si-NPN	UHF-A/Dr,30V,0,12A,0,6W,4GHz	51r	Tos	BFG34,BFG96

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2SC1555	Si-NPN	=2SC1554:1,2W	55r	Tos	BFQ34
2SC1556	Si-NPN	UHF-Dr/Out,30V,0,12W,Pq>0,13W(500MHz)	5g	Tos	BFR95
2SC1557	Si-NPN	UHF-Dr/Out,40V,0,18W,Pq>1W(1GHz)	5g	Tos	-
2SC1558	Si-NPN	UHF-A,15V,0,08A,0,25W,7GHz	51r	Tos	2SC2876,2SC3358,2SC3603
2SC1559	Si-NPN	UHF-A,15V,0,08A,0,4W,7GHz	51r	Tos	2SC2876,2SC3358,2SC3603
2SC156	Si-NPN	=2SC155:a=50	?36b	Fui	BC122..123,BC146,(BF254..255,..)
2SC1560	Si-NPN	UHF,LN,25V,0,07A,0,58W,4,5GHz	51s	Nec	BFP96,BFR96,BFQ73,2SC2844
2SC1561	Si-NPN	UHF-Dr/Out,55V,0,5A,Pq=3W(700MHz)	55r	Fui	2N4430
2SC1562	Si-NPN	UHF-Dr/Out,55V,1A,Pq=9W(700MHz)	55r	Fui	-
2SC1563	Si-NPN	UHF-Dr/Out,55V,2A,Pq=15W(700MHz)	55r	Fui	-
2SC1564	Si-NPN	UHF-Dr/Out,55V,4A,Pq=30W(700MHz)	55r	Fui	-
2SC1565	Si-NPN	AF,Sw-Pow,150/150V,0,25A,10W,150MHz	14h$	Mat	BD524,2SC2803,2SC3116
2SC1566	Si-NPN	Vid-Pow,250/250V,0,1A,4W,100MHz	14h$	Mat	BF415,BF417,BF458..459,2SC3417..
2SC1567	Si-NPN	AF,Sw-Pow,100/100V,0,5A,5W,120MHz	14h$	Mat	BD139,BD230,BD379,2SD1177..1178
2SC1567A	Si-NPN	=2SC1567:120/120V	14h$	-	2SC2690(A),2SD1382,2SD1563
2SC1568	Si-NPN	AF,Sw-Pow,18V,1A,4W,150MHz	14h$	Mat	BD135,BD226,BD375,2SD1380..
2SC1569	Si-NPN	Chroma-Out,300V,0,15A,12,5W,100MHz	17j$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC157	Si-NPN	GenP,20V,0,02A,0,125W,B=30	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1570	Si-NPN	55V,0.1A,0.2W,100MHz	-		-
2SC1570(NP)	Si-NPN	GenP,LN,55V,0,1A,0,2W,100MHz	7c	Sanyo	BC414,BC550,2SC2240,2SC2459..
2SC1571	Si-NPN	40V,0.1A,0.2W,100MHz	-		-
2SC1571(NP)(L)	Si-NPN	=2SC1570:40V,L:Ur<65mV	7c	Sanyo	BC184,BC413..414,BC550,2SC2240..
2SC1572	Si-NPN	HF,90V,0,05A,0,15W,100MHz	2a	Mit	BF422,BS538,BSW32,BSX21,2SC1890+
2SC1573	Si-NPN	200V,0.1A,1W,80MHz	-		-
2SC1573(NC)	Si-NPN	AF,Vid,250/200V,0,07A,1W,80MHz	7c(9mm)	Mat	BF422A,BF392..393,2SC3468..69..
2SC1573A	Si-NPN	=2SC1573:300/300V	7c(9mm)	-	BF420A,BF393,2SC3468..69,2SC4166,..
2SC1573B	Si-NPN	=2SC1573:400/400V	7c(9mm)	-	BF487,2SC2267,2SC3469,2SC4166..
2SC1574	Si-NPN	UHF,LN,20V,0,03A,0,4W,4,5GHz	5g	Tos	(BFQ63)
2SC1575	Si-NPN	-		Fui	-
2SC1576	Si-NPN	Sw,Pow,450/330V,8A,100W,10MHz	23a$	Toshiba	BUW24..26,BUX44,2SC2625,2SC4138..
2SC1577	Si-NPN	Sw,Pow,500/400V,8A,80W,7MHz	23a$	Sak	BUW25..26,BUW34..36,2SC3046,2SC4138..
2SC1578	Si-NPN	=2SC1577:600/500V	23a$	Sak	BUW25..26,BUW35..36,2SC3046,2SC4157..
2SC1579	Si-NPN	Sw,Pow,500/400V,15A,150W,5MHz	23a$	Sanken	BUW44..46,BUV25,BUX25,2SD641..
2SC158	Si-NPN	=2SC157:a=40	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1580	Si-NPN	=2SC1579:600/500V	23a$	Sak	BUW45..46,BUS13,BUX48,2SD641..
2SC1581	Si-NPN+Diode	AM-Pow,65V,7A,Pq=50W(30MHz)	59zb	Tos	-
2SC1582	Si-NPN+Diode	AM-Pow,65V,13A,Pq=100W(30MHz)	59zb	Tos	-
2SC1583	Si-NPN	Dual,LN,50V,0,1A,0,4W,150MHz	5-SIP/ba	Mit	2SC2259
2SC1584	Si-NPN	AF,Sw-Pow,150/100V,15A,150W,10MHz	23a$	Sak	MJ15015,2N3773,2SC2607..08,2SC3264..
2SC1585	Si-NPN	=2SC1584:200/150V	23a$	Sak	MJ15015,2SC2607..08,2SC3264,2SD753..
2SC1586	Si-NPN	=2SC1584:250/200V	23a$	Sak	MJ15022,2SC3263,2SD583
2SC1587	Si-NPN	UHF-Pow,45V,3A,Pq=30W(295MHz)	55r	Mit	BLX95,2N6105
2SC1588	Si-NPN	VHF-Dr/Out,36V,0,3A,Pq=0,4W(225MHz)	-	Nec	2SC1199,2SC1252,2SC1365,2SC1366..
2SC1589	Si-NPN	VHF-Dr/Out,36V,0,7A,Pq=1,5W(225MHz)	13g$	NEC	-
2SC159	Si-NPN	=2SC157:a=50	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1590	Si-NPN	VHF-Pow,36V,1,2A,Pq=7W(225MHz)	56k*	Nec	-
2SC1591	Si-NPN	VHF-Pow,36V,2,5A,Pq=15W(225MHz)	56k*	Nec	-
2SC1592	Si-NPN	UHF-A/Dr,30V,0,1A,3,5W,2,7GHz	55s	Nec	BFQ34,BFR94,2SC1255
2SC1593	Si-NPN	UHF-A/Dr,40V,0,15A,4,4W,2GHz	55s	Nec	BFQ34,BFR94,2SC1038,2SC1041..
2SC1594	Si-NPN	UHF-A/Dr,35V,0,2A,7W,2,5GHz	55s	Nec	BFT98,2SC1039,2SC1042
2SC1595	Si-NPN	UHF-A/Dr,35V,0,3A,7W,2,5GHz	55s	Nec	BFQ68,2SC1043,2SC1250..1251
2SC1596	Si-NPN	Vid/Sw,150/120V,0,05A,0,45W,130MHz	2a$	Fui	BF297..299,BF422,2SC3245A,2SC3248..
2SC1597	Si-NPN	Vid/Sw,150V,0,05A,0,45W,130MHz	2a$	Fui	BF297..299,BF422,2SC3245A,2SC3248..
2SC1598	Si-NPN	UHF-Dr/Out,50V,0,3A,6W,>2000GHz	55s	Nec	BFQ68
2SC1599	Si-NPN	UHF-Dr/Out,50V,0,3A,6W,>2000GHz	62a&	Nec	-
2SC16(A)	Si-NPN	GenP,25V,0,03A,0,25W,>100MHz	2a	Tos	BC168,BC183,BC238,BC548..
2SC160	Si-NPN	=2SC157:a=60	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1600	Si-NPN	UHF-Osc/Dr,40V,0,25A,Pq=0,7W(1,7GHz)	2a$	Nec	(2SC1253,2SC1366)
2SC1601	Si-NPN	GenP,LN,35V,0,1A,0,2W,200MHz	?2b	Njr	BC169,BC184,BC239,BC549,2SC2675+
2SC1602	Si-NPN	GenP,35V,0,1A,0,15W,200MHz	?2b	Njr	BC168,BC183,BC238,BC548,2SD767..
2SC1603	Si-NPN	UHF-Dr/Out,18V,0,6A,Pq=1,5W(485MHz)	55r	Mit	BLW42,BLW79,BLX66,BLY38
2SC1604	Si-NPN	UHF-Dr/Out,18V,0,3A,Pq=0,35W(485MHz)	51r	Mit	BLU98,MRF628,2N6256,2SC3019
2SC1605(A)	Si-NPN	VHF-Pow,35V,3,5A,Pq=16W(175MHz)	55r	Mit	BLY89,MRF209,2N5591,2N6082
2SC1606	Si-NPN	VHF-Dr/Out,40V,0,6A,Pq=3W(175MHz)	51r	Mit	BLW17,2SC1011,2SC1405

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2SC1607	Si-NPN	VHF/UHF, 40V, 0,1A, 0,18W	5g	Fui	BFX59
2SC1608	Si-NPN	UHF-Dr/Out, 40V, 0,5A, Pq=1,6W(470MHz)	51r	Fui	BLX66
2SC1609	Si-NPN	Sw, Pow, 140/120V, 25A, 120W, <500/2000nS	23a$	NEC	BD249D, BUV10, BUW57, BUX10, BUX40..
2SC161	Si-NPN	AF, Sw-Pow, 60V, 4A, 50W, 25MHz	23a$	Tos	BD245A, BDV91, 2N4914..15, 2SD895..
2SC1610	Si-NPN	Sw, Pow, 150/100V, 10A, 100W, <500/2000nS	23a$	Nec	BD245D, BDX11, BUW70, 2N3442..
2SC1611..1612	Si-NPN	-		Nec	-
2SC1613(A)	Si-NPN	Vid, 130V, 0,03A, 0,15W, 60MHz, A=ra	9c	Rhm	BF297..299, BF422, 2SC3467..68..
2SC1614	Si-NPN	=2SC1613: 180/180V	9c	Rhm	BF298..299, BF422, 2SC3248, 2SC3467,..
2SC1615	Si-NPN	=2SC1613: 210/210V	9c	Rhm	BF298..299, BF422, 2SC3467..68..
2SC1616	Si-NPN	-		Tos	-
2SC1617	Si-NPN	TV-HD, Sw, Pow, 300/100V, 7A, 50W	23a$	Toshiba	BU104, BU606..608, 2SD1154
2SC1618	Si-NPN	AF, Sw-Pow, 80V, 6A, 50W, 10MHz	23a$	Sak	BD245B, BD313, BDX93, 2N5874, 2SD895+
2SC1619	Si-NPN	=2SC1618: 100V	23a$	Sak	BD245C, BDW21C, BDX95, 2N5632..34..
2SC1619A	Si-NPN	=2SC1619: 120V	23a$	-	BD245C, BDX12, 2N4348, 2N5633..34..
2SC162	Si-NPN	VHF-A/Dr, 30V, 0,25A, 0,5W, 500MHz	2a$	Oki	BFW16..17, BFX55, 2N3866
2SC1620(Z)	Si-NPN	UHF-Dr/Out, 36V, 0,6A, Pq=2,6W(500MHz)	51r	Mat	BLX66
2SC1621	Si-NPN	Sw, 25V, 0,2A, <20/40nS	35a	NEC	BSV52, 2SC3578, 2SC4699K
2SC1621-B2	Si-NPN	-	35	Nec	→2SC1621
2SC1621-B3	Si-NPN	-	35	Nec	→2SC1621
2SC1621-B4	Si-NPN	-	35	Nec	→2SC1621
2SC1622	Si-NPN	GenP, 40V, 0,1A, 110MHz	35a	Nec	BC846..847, BCW71..72, BCW81..
2SC1622A	Si-NPN	=2SC1622: 120V	35a	-	2SC3324, 2SC4050
2SC1622A-D15	Si-NPN	-	35	Nec	→2SC1622A
2SC1622-D5	Si-NPN	-	35	Nec	→2SC1622
2SC1622-D6	Si-NPN	-	35	Nec	→2SC1622
2SC1624	Si-NPN	AF, Sw-Pow, 120V, 1A, 15W, 30MHz	17j$	Tos	BD941, 2SC2275, 2SD1516, 2SD1562..
2SC1625	Si-NPN	=2SC1624: 100V	17j$	Tos	BD239C, BD939, 2SC2275, 2SD1562..
2SC1626	Si-NPN	=2SC1624: 80V, 0,75A, 100MHz	17j$	Tos	2SC2275, 2SD1561, (BD239B, BD937,..)
2SC1627	Si-NPN	GenP, 80V, 0,3A, 0,6W, 100MHz	7c	Mic, Tos	BC639, 2SC3665, 2SC4414, 2SD1226..
2SC1627A	Si-NPN	=2SC1627: 0,4A, 0,8W	7c(9mm)	-	2SC2235, 2SC3939, 2SD667, 2SD1211..
2SC1628	Si-NPN	Vid, 180/150V, 0,05A, 120MHz	13g$	Toshiba	BF460..462, MPSU10, 2SC2224(A)..
2SC1629	Si-NPN	Hi-beta, 90V, 8A, 50W, B>500	23a$	Sanken	2SC1831, 2SC2199, 2SD1831
2SC163	Si-NPN	=2SC162: 50V	2a$	Oki	BFW16..17, BFX55, 2N3866
2SC1630	Si-NPN	Vid, 175/175V, 0,03A, 0,75W, 100MHz	2a$	Son	BF258..259, 2N5058..59, 2SC3467..68..
2SC1631	Si-NPN	GenP, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC169, BC184, BC239, BC549, 2SC2675+
2SC1632	Si-NPN	=2SC1631: 50V	7c	Son	BC184, BC414, BC550, 2SC2240..
2SC1633	Si-NPN	GenP, 25V, 0,2A, 0,25W, 140MHz	7c	Son	BC168, BC183, BC238, BC548, 2SD767..
2SC1634	Si-NPN	=2SC1633: 50V	7c	Son	BC167, BC182, BC237, BC547, 2SD767..
2SC1635(F)	Si-NPN	Sw, 70V, 1A, 0,8W, <35/55nS	2a$	Fui	BSS27, BSV95, 2N3735, 2SC1386
2SC1636	Si-NPN	Hi-beta, Hi-Ueb, LN, 50V, 0,02A, 30MHz	10b	Son	2SC3069, 2SC3615, 2SC3820, 2SD1915
2SC1637	Si-NPN	Hi-Ueb, 50V, 0,02A, 0,25W, 20MHz	10b	Son	2SC2878, 2SC3114, 2SC3135, (BC547,..)
2SC1638	Si-NPN	UHF-A/Dr, 40V, 0,3A, 0,6W, 1,4GHz	5g	Fui	2SC1199, 2SC1252, 2SC1365..1366
2SC1639	Si-NPN	GenP, 25V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC168, BC183, BC238, BC548, 2SC1890+
2SC164	Si-NPN	=2SC162: 60V	2a$	Oki	BFW16..17, BFX55, 2N3866
2SC1640	Si-NPN	GenP, LN, 25V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC169, BC184, BC239, BC549, 2SC2390+
2SC1641	Si-NPN	GenP, 40V, 0,15A, 0,3W, 250MHz	7c	Rhm	BC167, BC182, BC237, BC547, 2SD767..
2SC1642	Si-NPN	=2SC1641: 25V	7c	Rhm	BC168, BC183, BC238, BC548, 2SD767..
2SC1643	Si-NPN	AF, Sw, 40V, 0,03A, 0,25W, <200/300nS	7c	Rhm	BC237, BC547, BSW41, BSY63, 2N708,..
2SC1644	Si-NPN	=2SC1643: 25V	7c	-	BC238, BC548, BSY62..63, 2N706A..
2SC1645(S)	Si-NPN-Darl	=2SC1545:	7c, 41c	Rhm	→2SC1545
2SC1646	Si-NPN-Darl	=2SC1546:	7c	Rhm	→2SC1546
2SC1647	Si-NPN	GenP, 50V, 0,03A, 0,25W, 200MHz	7c	Rhm	BC167, BC182, BC237, BC547, 2SC1890+
2SC1648	Si-NPN	=2SC1647: ra	7c	Rhm	BC414, BC550, 2SC2240, 2SC2459..
2SC1649	Si-NPN	=2SC1613: 0,25W	7c	Rhm	→2SC1613
2SC165	Si-NPN	=2SC162: 60V	2a$	Oki	BFW16..17, BFX55, 2N3866
2SC1650	Si-NPN	=2SC1614: 0,25W	7c	Rhm	→2SC1614
2SC1652(M)	Si-NPN	GenP, 40V, 0,5A, 0,3W, 250MHz	9c	Rhm	BC337, BC635, BC637, 2SC3377..
2SC1653	Si-NPN	Sw, Nix, 150/130V, 0,05A, 120MHz	35a	NEC	BF822, BFN24, 2SC3143, 2SC3360..
2SC1653-N2	Si-NPN	-	35	Mot, Nec	→2SC1653
2SC1653-N3	Si-NPN	-	35	Mot, Nec	→2SC1653
2SC1653-N4	Si-NPN	-	35	Mot, Nec	→2SC1653
2SC1653-N5	Si-NPN	-	35	Mot, Nec	→2SC1653
2SC1653-N6	Si-NPN	-	35	Mot, Nec	→2SC1653
2SC1653-N7	Si-NPN	-	35	Mot, Nec	→2SC1653

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2SC1654	Si-NPN	=2SC1653: 180/160V	35a	Nec	BF822, BFN24, 2SC3143, 2SC3360..
2SC1655(A)	Si-NPN	UHF, 16V, 0,03A, 0,15W, 8GHz	52s	Nec	BFG65, BFQ66, 2SC3267, 2SC3586..87
2SC1656	Si-NPN	UHF, 10V, 0,03A, 0,15W, 7GHz	52s	Nec	BFG65, BFQ66, 2SC3267, 2SC3586..87
2SC1657	Si-NPN	=2SC1655: Dual	-	Nec	-
2SC1658	Si-NPN	=2SC1656: Dual	-	Nec	-
2SC1659	Si-NPN	UHF, 20V, 0,08A, 0,5W, 7GHz	51s	Nec	2SC2876, 2SC3358, 2SC3603
2SC166	Si-NPN	HF/Sw, 30V, 0,03A, 0,2W	2a	Hit	BC168, BC183, BC238, BC548..
2SC1660	Si-NPN	UHF, 20V, 0,08A, 0,5W, 7GHz	51s	Nec	2SC2876, 2SC3358, 2SC3603
2SC1661	Si-NPN	=2SC1659: Dual	-	Nec	-
2SC1662	Si-NPN	=2SC1660: Dual	-	Nec	-
2SC1662A-D16	Si-NPN	-	35	Nec	→2SC1662A
2SC1662A-D17	Si-NPN	-	35	Nec	→2SC1662A
2SC1662A-D18	Si-NPN	-	35	Nec	→2SC1662A
2SC1662-D7	Si-NPN	-	35	Nec	→2SC1662
2SC1662-D8	Si-NPN	-	35	Nec	→2SC1662
2SC1663	Si-NPN	Sw, Vid-Pow>140/140V, 0,5A, 7,9W, 50MHz	13g$	Sony	BF460..462, MPSU10, 2SC2224(A)..
2SC1664	Si-NPN	Hi-beta, 70V, 6A, 40W, B>500	22a$	Sak	2SC2315..16, 2SC2491, 2SD1158
2SC1664A	Si-NPN	=2SC1664: 100V	22a$	-	2SC2198, 2SC2491, 2SC2316
2SC1665	Si-NPN	UHF, 25V, 0,02A, 0,2W, 1,4GHz	5g	Nec	BF689, BFX62, BFX89, 2N2857
2SC1666	Si-NPN	VHF-Dr/Out, 40V, 0,3A, 0,6W, 700MHz	5g	Nec	BFX55, 2SC1199, 2SC1252, 2SC1365..66
2SC1667	Si-NPN	AF, Sw-Pow, 90V, 4A, 50W(Tc=75°), 10MHz	23a$	Mat	BD245C, BD313, BDX95, 2N5758..59..
2SC1668	Si-NPN	HF-Pow, 35V, 6A, 40W, 400MHz	55r	Tos	BLW20, BLW31, 2N6084
2SC1669	Si-NPN	AF, Sw-Pow, 150/150V, 1,5A, 25W, 6MHz	17j$	Tos	2SC2073, 2SD578, 2SD608(A), 2SD1138..
2SC167	Si-NPN	=2SC166: 55V	2a	Hit	BC167, BC182, BC237, BC547..
2SC1670	Si-NPN	Vid, 140/140V, 0,5A, 0,75W, 50MHz	7c(9mm)	Son	2SC2383, 2SC3228, 2SD1812
2SC1671	Si-NPN	-		Tos	-
2SC1672	Si-NPN	Sw, Pow, 150/120V, 25A, 120W, <500/1000nS	23a$	Nec	BD249D, BDW32, BUW39, BUW49..
2SC1673	Si-NPN	UHF-A/Dr, 35V, 0,3A, 7W, 2,5GHz	55s	Nec	BFQ68, BFT99
2SC1674	Si-NPN	FM-Preamp/Mix/Osc, 30V, 20mA, 600MHz	7c	Nec	BF225, BF310, BF314, BF502, BF505..
2SC1675	Si-NPN	AM/FM-Pre/Mix/Osc, 50V, 30mA, 250MHz	7c	Nec	BF240..241, BF254..255, BF594..595,..
2SC1676	Si-NPN	VHF-Pow, 50V, 3A, Pq>10W(270MHz)	55r	Tos	BLX95, 2N6105, 2SC2894
2SC1677	Si-NPN	VHF-Pow, 50V, 5A, Pq>19W(270MHz)	55r	Tos	-
2SC1678	Si-NPN	AM-Pow, 65V, 3A, Pq>3W(27MHz)	17j$	Tos	2SC1306, 2SC1909, 2SC1964, 2SC2078..
2SC1679	Si-NPN	AM-Pow, 65V, 3A	17j$	Tos	2SC1306, 2SC1909, 2SC1964, 2SC2078..
2SC168	Si-NPN	Sw, 20V, 0,2A, 0,2SW, <50/60nS	2a$	Oki	BSS11..12, BSY17..18, 2N2369..69(A),..
2SC1680	Si-NPN	VHF-Pow, 35V, 2A, Pq=8W(175MHz)	55r	Tos	BLW19, BLW37, MRF212, 2N5590
2SC1681	Si-NPN	GenP, LN, 60V, 0,05A, 0,2W, 130MHz	7c	Tos	2SC1775(A), 2SC2089, 2SC2240, 2SC2390,..
2SC1682	Si-NPN	=2SC1681: 40V	7c	Tos	BC184, BC414, BC550, 2SC2390..
2SC1683(A)	Si-NPN	AF, Sw-Pow, TV-VD, 200V, 0,5A, 30W, 6MHz	17j$	Mat	BD239F, 2SC2238B, 2SC2660, 2SD1138
2SC1684(NC)	Si-NPN	GenP, 30V, 0,1A, 0,25(NC=0,5)W, 150MHz	7c	Mat,Mic	BC168, BC183, BC238, BC548, 2SC2675+
2SC1685	Si-NPN	GenP, 60V, 0.1A, 150MHz	-		-
2SC1685(NC)	Si-NPN	=2SC1684: 60V	7c	Mat,Mic	BC174, BC182, BC190, BC546, 2SC2675+
2SC1686	Si-NPN	HF/AF, 40V, 25mA, 0,25W, 330MHz	7d	Mat	BF198..199, BF224..225, BF596..597,..
2SC1687	Si-NPN	HF/AF, 40V, 30mA, 0,4W, 550MHz	7d	Mat,Mic	BF198..199, BF224..225, BF596..597,..
2SC1688	Si-NPN	=2SC1687: 50V	7d	Mat	BF198..199, BF224..225, BF596..597,..
2SC1689	Si-NPN	VHF-Pow, 55V, 3A, Pq=26W(220MHz)	55r	Mit	BLX95, 2N6105
2SC169	Si-NPN	=2SC168: 40V, <40/44nS	2a$	Oki	BSS11, BSX19..20, 2N2369..69(A)..
2SC1690..1697	Si-NPN	-		Org	-
2SC1698	Si-NPN-Darl	Sw, Pow, 210V, 10A, 125W, B>1000	23a$	Org	BUW28, BUW67, 2SD1027, 2SD1515..
2SC1699..1702	Si-NPN	-		Org	-
2SC17(A)	Si-NPN	GenP, 25V, 0,05A, 0,25W, 150MHz	2a$	Tos	BC168, BC183, BC238, BC548..
2SC170	Si-NPN	HF, 25V, 0,05A, 0,11W, 250MHz	2a$	Fui	BF240..241, BF254..255, BF594..595,..
2SC1703	Si-NPN-Darl	Sw, Pow, 600V, 1SA, 150W, B>100	23a$	Org	BUT51, MJ10008..9, 2SD683, 2SD606..
2SC1704..1705	Si-NPN	-		Org	-
2SC1706(H)	Si-NPN	Vid, 200V, 0,05A, 0,2W, 60MHz	2a$	Hit	BF298..299, BF422, 2SC3467..68..
2SC1707(H)	Si-NPN	GenP, 40V, 0,1A, 0,2W, >100MHz	2a$	Hit	BC167, BC183, BC238, BC548, 2SD767..
2SC1707A(AH)	Si-NPN	=2SC1707: 70V	2a$	-	BC174, BC182, BC190, BC546, 2SC2240+
2SC1708	Si-NPN	GenP, LN, 90V, 0,05A, 0,2W, 150MHz	7b	Mit	2SC1775(A), 2SC1845, 2SC2240, 2SC2459,..
2SC1708A	Si-NPN	=2SC1708: 120V	7b	-	2SC1775A, 2SC1845, 2SC2240, 2SC2459,..
2SC1709	Si-NPN	Sw, 30V, 0,3A, 0,3W, -/125nS	7a	Fui	BSW41, BSX48, BSY63, 2N708, 2N914..
2SC171	Si-NPN	=2SC170: 0,2W	2a$	Fui	BF240..241, BF254..255, BF594..595,..
2SC1710	Si-NPN	UHF-Dr/Out, 15V, 0,13A, 1W, 7GHz	?55r	Fui	-
2SC1711(A)	Si-NPN	UHF, LN, 20V, 0,03A, 0,2W, 7,5GHz	52r	Fui	BFG65, BFQ66, 2SC1655..56, 2SC3276
2SC1712	Si-NPN	UHF, 16V, 0,03A, 0,2W, 8GHz	52r	Fui	BFG65, BFQ66, 2SC1655..56, 2SC3276

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2SC1713	Si-NPN	=2SC1712:Dual	-	Fui	-
2SC1714	Si-NPN	=2SC1712:Dual	-	Fui	-
2SC1715	Si-NPN	=2SC1712:Dual	-	Fui	-
2SC1716	Si-NPN	=2SC1712:Dual	-	Fui	-
2SC1717	Si-NPN	VHF-Pow,40V,1A,Pq=2,2W(220MHz)	43a*	Tos	-
2SC1718	Si-NPN	VHF-Pow,35V,4,5A,Pq=14W(220MHz)	55r	Tos	MRF209
2SC1719	Si-NPN	Vid,150/120V,0,05A,1W,130MHz	2a$o	Fui	2SC2631..32,2SC3245A,2SC3248,2SC3467+
2SC172(A)	Si-NPN	HF,25(A=40)V,0,05A,0,3W,350MHz	2a$	Fui	BF198..199,BF224..225,BF505..
2SC1720	Si-NPN	=2SC1719:150/150V	2a$o	Ful	2SC2631..32,2SC3245A,2SC3248,2SC3467+
2SC1721	Si-NPN	GenP,80V,1A,0,5W,>100MHz	7c	Fui	BC639,2SD667,2SD1226,2SD1768..
2SC1722	Si-NPN	Vid-Pow,300V,0,2A,12,5W,80MHz	17j$	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC1723	Si-NPN	=2SC1722:15W,60MHz	17j$	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC1724	Si-NPN	UHF-Dr/Out,35V,0,8A,Pq=4W(470MHz)	55r	Tos	BLW43,BLW80,2N5945
2SC1725	Si-NPN	UHF-Pow,35V,1,4A,Pq=7W(470MHz)	55r	Tos	BLU97,BLW14,BLX68,BLY53
2SC1726	Si-NPN	UHF-Pow,35V,2,8A,Pq=13W(470MHz)	55r	Tos	BLW15,BLX69,2SC1338,2SC1404
2SC1727	Si-NPN	VHF,LN,AGC,700MHz	7f	Son	BF314,BF502,BF505,BF507,BF959..
2SC1728	Si-NPN	AF,Sw-Pow,100V,1A,7,9W,80MHz	13g$	Sony	BD419,BD529,2SC2384
2SC1729	Si-NPN	VHF-Pow,35,3,5A,Pq=16W(175MHz)	58s*	Mit	-
2SC173	Ge-NPN	HF,15V,5mA,0,03W,20MHz	?2e	Son	-
2SC1730	Si-NPN	VHF/UHF,30V,0,05A,1100MHz	7c	Nec	BF377..378,BF689K,BF763,2N2857..
2SC1731	Si-NPN	Dual,UHF,20V,0,05A,3GHz	-	Nec	-
2SC1732	Si-NPN	Dual,UHF,20V,0,05A,3GHz	-	Nec	-
2SC1733	Si-NPN	Dual,UHF,30V,0,05A,2GHz	84bg1	Nec	-
2SC1734(H)	Si-NPN	GenP,LN,40V,0,03A,0,1W,300MHz	2a$	Hit	BC184,BC414,BC550,2SC2390..
2SC1735	Si-NPN	GenP,100V,0,5A,0,8W,130MHz	7b	Mit	BC639,2SC3665,2SD667(A),2SD1616A..
2SC1736	Si-NPN	GenP,50V,0,1A,0,3W,300MHz	7a	Mit	BC167,BC182,BC237,BC547,2SD767..
2SC1737	Si-NPN	=2SC1736:35V	7a	Mit	BC168,BC183,BC238,BC548,2SD767..
2SC1738	Si-NPN	=2SC1636:ra,35V	7a	Mit	BC169,BC184,BC239,BC549,2SC2675+
2SC1739	Si-NPN	GenP,20V,32mA,0,25W,300MHz	7c	Rhm	BC183,BC238,BC548,BF254..255..
2SC174	Si-NPN	HF,30V,25mA,0,2W,170MHz	5g	Fui	BF240..241,BF254..255,BF594..595,..
2SC1740LN(SLN)	Si-NPN	=2SC1740:ra	7c	-	BC184,BC414,BC550,2SC2677..75..
2SC1740S	Si-NPN	GenP,50V,0,1A,0,3W,180MHz	41c	Rhm	BC167,BC182,BC237,BC547,2SD767..
2SC1741	Si-NPN	40V,0.5A,0.3W,250MHz	-		-
2SC1741(S)	Si-NPN	=2SC1652:	7c,41c	Rhm	→2SC1652
2SC1741A(AS)	Si-NPN	=2SC1652:50V,0,4W	7c,41c	-	→2SC1652
2SC1742	Si-NPN	UHF,LN,20V,0,03A,0,15W,6,5GHz	51r	Tos	BFQ57..58,BFQ74,2SC1655..1656..
2SC1743	Si-NPN	UHF,LN,20V,0,03A,0,175W,4,5GHz	51r	Tos	BFQ71,BFT75,2SC1119,2SC1336..
2SC1744	Si-NPN	VHF-Pow,35V,10A,Pq=44W(175MHz)	60c*	Tos	-
2SC1745	Si-NPN	GenP,LN,60V,0,05A,0,15W,140MHz	2a$	Tos	2SC1775(A),2SC2088..2089,2SC2240..
2SC1746(A)	Si-NPN	=2SC1745:50V	2a$	Tos	BC414,BC550,2SC2088..89,2SC2240..
2SC1747	Si-NPN	UHF-A/Dr,40V,0,1A,0,3W,>1400MHz	5g	Hit	BFX59
2SC1748	Si-NPN	Sw,Vid,300/300V,0,1A,0,8W,50MHz	2a$	Nec	BF259,BFR59,BFS89,2N5058,2SC3468+
2SC1749	Si-NPN	Vid-Pow,300/220V,0,1A,10W,90MHz	17j$	Mit	2SC1505..1507,2SC1755..1757,2SC1905
2SC174A	Si-NPN	=2SC174:60V	5g	-	(BF240..241,BF254..255,BF594..595,..)
2SC175	Ge-NPN	HF/AF,15V,5mA,0,03W,10MHz	?2e	Son	-
2SC1750..1751	Si-NPN	-		Sanyo	-
2SC1752	Si-NPN	=MPSA42	7e	Mot	→MPSA42
2SC1753	Si-NPN	=MPSA43	7e	Mot	→MPSA43
2SC1754	Si-NPN	=2N6426	7e	Mot	→2N6426
2SC1755	Si-NPN	AF/Vid-Out-Pow,300/300V,0,2A,>50MHz	17j$	Sanyo	2SC1505..1507,2SC1905
2SC1756	Si-NPN	=2SC1755	17j$	Sanyo	2SC1505..1507,2SC1905
2SC1757	Si-NPN	=2SC1755	17j$	Sanyo	2SC1505..1507,2SC1905
2SC1758	Si-NPN	Vid-Pow,300/300V,0,1A,10W,80MHz	13g$	NEC	BF382,MPSU10,(BF617,BF859,..)
2SC1759	Si-NPN	-		Nec	-
2SC176	Ge-NPN	HF/AF,15V,5mA,0,03W,10MHz	?2e	Son	-
2SC1760	Si-NPN	AF,Sw-Pow,100V,1A,7,9W,80MHz	13j$	Sony	2SC2275(A),2SC2483,(BD419,BD529..)
2SC1761	Si-NPN	AF,Sw-Pow,20V,2A,80MHz	13j$	Sony	2SC1173,2SC1226,2SC1398,2SC1848..
2SC1762-1	Si-NPN	Sw,700/400V,0,3A,0,47W,13MHz	2a$	Son	2N5012..5015,2SD594
2SC1762-2	Si-NPN	=2SC1762-1:800/450V	2a$	-	2N5012..5015,2SD594
2SC1763	Si-NPN	AM-Pow,65V,7A,Pep=40W(30MHz)	59r	Tos	-
2SC1764	Si-NPN	AM-Pow,65V,12A,Pep=80W(28MHz)	59r	Tos	MRF463..464
2SC1765	Si-NPN	UHF-Dr/Out,35V,0,8A,Pq=3,2W(470MHz)	43a*	Tos	-
2SC1766	Si-NPN	GenP,30V,0,1A,0,31W,230MHz	7e	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC1767	Si-NPN	-		Hit	-

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2SC1768	Si-NPN	Hi-beta,200V,5A,50W,B>400	23a$	Sanken	2SC1829,2SD1090
2SC1769	Si-NPN	GenP,30V,0,05A,0,2W,200MHz	7e	Njr	BC168,BC183,BC238,BC548,2SC1890+
2SC177	Ge-NPN	HF/AF,15V,5mA,0,03W,10MHz	?2e	Son	-
2SC1770	Si-NPN	GenP,30V,0,2A,0,3W,100MHz	7e	Njr	BC168,BC183,BC238,BC548,2SD767..
2SC1771	Si-NPN	GenP,60V,0,2A,0,3W,100MHz	7e	Njr	BC174,BC182,BC190,BC546,2SC1815+
2SC1772	Si-NPN	GenP,95V,0,05A,0,3W,40MHz	7e	Njr	2SC1890(A),2SC2240,2SC2363,2SC2674,..
2SC1773	Si-NPN	GenP,30V,0,4A,0,5W,100MHz	7e	Njr	BC337..338,BC635,BC637,2SC3377..
2SC1774	Si-NPN	=2SC1773:60V	7e	Njr	BC337A,BC637,BC639,2SD1226..
2SC1775	Si-NPN	GenP,LN,90V,0,05A,0,3W,200MHz	7c	Hit	2SC2088..89,2SC2240,2SC2362,2SC2389..
2SC1775A	Si-NPN	=2SC1775:120V	7c	-	2SC2088,2SC2240,2SC2362,2SC2389..
2SC1776	Si-NPN	GenP,60V,0,25A,0,3W,220MHz	7a	Fui	BC174,BC182,BC190,BC546,2N3904..
2SC1777	Si-NPN	AF,Sw-Pow,70V,6A,50W,10MHz	23a$	Sak	BD245A,BDV93,BDX93,2N5874..
2SC1778	Si-NPN	VHF/UHF,25V,15mA,650MHz	7d	Mat,Mic	BF377..378,BF689K,BF763,2N2857..
2SC1779(A,B)	Si-NPN	VHF/UHF,AGC,30V,20mA,675MHz	7d	Mat	BF377..378,BF689K,BF763,2N2857..
2SC178	Ge-NPN	HF/AF,15V,5mA,0,03W,20MHz	?2e	Son	-
2SC1780	Si-NPN	UHF,LN,25V,15mA,0,15W,3GHz	9c	Mat	BFR15,BFS55,BFT66..67,BFW99
2SC1781	Si-NPN	50V,0.5A,0.35W	-		-
2SC1781(H)	Si-NPN	GenP,70V,0,5A,0,35W,150MHz	2a$	Hit	BC639,2N2221A..22A,2SC4414,2SD1226..
2SC1782	Si-NPN	AF,Sw-Pow,140/80V,10A,100W,10MHz	23a$	Sak	BD245D,BDX11,2N3442,2SC2706..
2SC1783	Si-NPN	=2SC1782:180/120V	23a$	Sak	BD245E,BDW14,2SC3263,2SD555..
2SC1784	Si-NPN	Sw,Pow,150/150V,15A,100W,-/3,1µS	23a$	Sanken	BDW12,BUX41,2SD552,2SD1047..
2SC1785	Si-NPN	=2SC1784:200/200V	23a$	SAk	BDW16,BUX41,2SC3263..64,2SD552..
2SC1786	Si-NPN	=2SC1784:230/230V	23a$	Sak	BUX41,2SC1586,2SC3263..64,2SD583..
2SC1787	Si-NPN	GenP,LN,35V,0,03A,0,15W,150MHz	9c	Mat	BC169,BC184,BC239,BC549,2SC2390+
2SC1788(A)	Si-NPN	GenP,25V,0,5A,0,6W,150MHz	7c	Mat,Mic	BC337..338,BC635,BC637,BC639..
2SC1789	Si-NPN	VHF/IF,25V,50mA,0,4W,>600MHz	7c	Mat,Mic	BF377..378,BF689K,BF763,2N2857..
2SC179	Ge-NPN	Sw,25V,0,4A,0,12W,3MHz	2a	Hit	ASY73..75
2SC1790	Si-NPN	UHF,25V,15mA,0,15W,3GHz	5g	Mat	BFR15,BFS55,BFT66..67,BFW99
2SC1791	Si-NPN	UHF-Dr/Out,45V,1A,Pq=6W(1GHz)	55s	Nec	-
2SC1792	Si-NPN	UHF-Pow,45V,2A,Pq=10W(1GHz)	55s	Nec	-
2SC1793	Si-NPN	VHF-Pow,45V,4A,42W,>300MHz	55s	Nec	BLW75,MRF314A,2N5642
2SC1794..1796	Si-NPN	-		Nec	-
2SC1797	Si-NPN	UHF-Dr/Out,50V,0,3A,Pq=1,6W(2GHz)	62a&	Nec	-
2SC1798	Si-NPN	UHF-Dr/Out,50V,1A,Pq=3,1W(2GHz)	62a&	Nec	-
2SC1799	Si-NPN	UHF-Pow,50V,2A,Pq=6,3W(2GHz)	62a&	Nec	-
2SC18	Si-NPN	GenP,25V,0,03A,0,25W	2a$	Tos	BC168,BC183,BC238,BC548..
2SC180	Ge-NPN	=2SC179:5MHz	2a	Hit	ASY73..75
2SC1800	Si-NPN	UHF-Pow,50V,3A,Pq>10W(2GHz)	62a&	Nec	-
2SC1801	Si-NPN	UHF,30V,0,03A,1300MHz	7e	Njr	BF377..378,BF689K,BF763,2N2857..
2SC1802	Si-NPN	VHF/UHF,30V,0,02A,700MHz	7e	Njr	BF377..378,BF689K,BF763,2N2857..
2SC1803	Si-NPN	UHF-A/Dr,30V,0,13A,0,58W,2,7GHz	51s	Nec	BFG34
2SC1804	Si-NPN	UHF-Pow,47V,1A,Pq=4,5W(770MHz)	55r	Mit	-
2SC1805	Si-NPN	UHF-Pow,45V,2A,Pq=12W(700MHz)	55r	Mit	-
2SC1806	Si-NPN	UHF-Pow,45V,4A,Pq=26W(700MHz)	55r	Mit	-
2SC1807(TX)	Si-NPN	UHF-Osc,18V,0,1A,Pq=25mW(485MHz)	5g	Mit	BFX59
2SC1808	Si-NPN	UHF-Dr/Out,35V,1A,Pq=3,5W(485MHz)	55r	Mit	BLW43,BLW80
2SC1809(S)	Si-NPN	FM,25V,20mA,500MHz	7c,41c	Rhm	BF225,BF310,BF314,BF502,BF505..
2SC181	Ge-NPN	=2SC179:10MHz	2a	Hit	ASY73..75
2SC1810	Si-NPN	TV-HÜ/SMPS,700/300V,0,3A,7,9W	13j$	Sony	2SC3184,2SD1527
2SC1811(-1,-2)	Si-NPN	Vid,240/150V,0,1A,0,75W,140MHz	7c(9mm)	Son	BF298..299,BF422(A),2SC3468..
2SC1812	Si-NPN	UHF,AGC,22V,0,02A,1100MHz	25u	Son	2SC2144,2SC2353,2SC2464,2SC2466..
2SC1813	Si-NPN	GenP,50V,0,5A,0,5W,100MHz	7e	Son	BC337,BC635,BC637,2SC4414..
2SC1814	Si-NPN	-		Tos	-
2SC1815	Si-NPN	GenP,60V,0,15A,0,4W,>80MHz	7c	Toshiba	BC174,BC182,BC190,BC546,2SD767..
2SC1815BL	Si-NPN	60V,0.15A,0.4W,B>350	-		-
2SC1815GR	Si-NPN	60V,0.15A,0.4W,B>200	-		-
2SC1815L	Si-NPN	=2SC1815:ra	7c	-	BC550,2SC2240,2SC2674..75,2SC3378
2SC1815Y	Si-NPN	60V,0.15A,0.4W,B>120	-		-
2SC1816	Si-NPN	AM-Pow-Sw,100V,4A,Pq=6W(27MHz)	17j$	Son	2SC1306,2SC1909,2SC2043,2SC2092
2SC1816H	Si-NPN	=2SC1816:Hi-rel,200V	17j$	-	-
2SC1817	Si-NPN	AM-Pow,45V,5A,Pq=21W(27MHz)	17j$	Son	-
2SC1818	Si-NPN	AF,Sw-Pow,130V,7A,100W,7MHz	23a$	Mat	2SC2260..2262,2SD551,2SD731..732..
2SC1819	Si-NPN	Vid-Pow,300/300V,0,1A,15W,100MHz	17j$	Mat	2SC1505..1507,2SC1755..1757,2SC1905
2SC182	Si-NPN	AF-Pow,25V,0,15A,0,15W,90MHz	24b	Nec	BC168,BC183,BC238,BC548,2SD767..

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2SC1820	Si-NPN	VHF-Dr/Out,55V,0,5A,Pq=1,6W(175MHz)	2a	Fui	BFS23,BFW47,BLY34,2N3553,2N5160
2SC1821	Si-NPN	UHF-Dr/Out,55V,0,5A,Pq=4W(470MHz)	55r	Fui	BLW90,2SC2892
2SC1822	Si-NPN	UHF-Pow,55V,1A,Pq=7,5W(470MHz)	55r	Fui	BLX93,2SC1040,2SC2700
2SC1823	Si-NPN	UHF-Pow,55V,2A,Pq=15W(470MHz)	55r	Fui	BLW94,BLX94,MRF323,2SC1118
2SC1824	Si-NPN	UHF-Pow,55V,4A,Pq=30W(470MHz)	55r	Fui	BLX95,2N6105
2SC1825	Si-NPN	UHF-Pow,55V,8A,Pq=55W(470MHz)	?57s	Fui	2N6439,2SC2796
2SC1826	Si-NPN	AF,Sw-Pow,80V,4A,30W,10MHz	17j$	Sak	BD243B,BD537,BD539B,BD951..
2SC1827	Si-NPN	=2SC1826:100V	17j$	Sak	BD243C,BD539C,BD953,2SD712..
2SC1828	Si-NPN	Sw,Pow,800/400V,1A,40W,7MHz	22a$	Sak	BUV36,BUX84..85,2SC3149,2SC3352
2SC1829	Si-NPN	Hi-beta,200/150V,5A,100W,B>400	23a$	Sanken	2SD1090
2SC183(A)	Si-NPN	HF/AF,20(A=30)V,0,03A,0,1W,150MHz	24b	Nec	BF240..241,BF254..255,BF594..595,..
2SC1830	Si-NPN-Darl	140/140V,15A,150W,B>500	23a$	Sanken	2SD710
2SC1831	Si-NPN	Hi-beta,90V,8A,100W,B>500	23a$	Sanken	2SD1831
2SC1832	Si-NPN-Darl	Sw,Pow,500/400V,15A,150W,B>100	23a$	Sanken	BU932,2SD711(A),2SD572..573,2SD683
2SC1832-O	Si-PNP	-	35(1,6mm)	Tos	→2SA1832
2SC1833	Si-NPN	GenP,60V,0,2A,0,3W,300MHz	7c	Nec	BC182,BC546,BSV59,2N2221..22(A),..
2SC1834	Si-NPN	Sw,60V,0,2A,0,3W,<20/40nS	7c	Nec	-
2SC1835	Si-NPN	HF-Pow,25V,1A,8W,500MHz	-	Mit	-
2SC1836	Si-NPN	VHF-Pow,25V,5A,30W,500MHz	55r	Mit	BLW20,BLW31,2N6084
2SC1837(Z)	Si-NPN	UHF-Dr/Out,35V,0,6A,Pq=1W(2GHz)	62d*	Fui	-
2SC1838(Z)	Si-NPN	UHF-Dr/Out,35V,1,5A,Pq=3W(2GHz)	62d*	Fui	-
2SC1839	Si-NPN	-		Nec	-
2SC184	Si-NPN	AM-Pre/Mix,20V,0,03A,0,1W,200MHz	24b	Nec	BF240..241,BF254..255,BF594..595,..
2SC1840	Si-NPN	GenP,40V,0,1A,0,5W,100MHz	7c	Nec	BC167,BC182,BC237,BC547,2SD767..
2SC1841	Si-NPN	GenP,120/120V,0,05A,0,5W,110MHz	7c	Nec	2SC1890A,2SC2363,2SC2240,2SC2459..
2SC1842	Si-NPN	GenP,LN,40V,0,1A,0,25W,250MHz	7c	Nec	BC184,BC413..414,BC550,2SC2240..
2SC1843	Si-NPN	=2SC1842:60V,100MHz	7c	Nec	BC414,BC550,2SC2240,2SC2459..
2SC1844	Si-NPN	GenP,LN,60V,0,1A,0,5W,100MHz	7c	Nec	BC414,BC550,2SC2240,2SC2459..
2SC1845	Si-NPN	GenP,LN,120V,0,05A,0,5W,110MHz	7c	Nec	2SC1775A,2SC1845,2SC2240,2SC2459..
2SC1846	Si-NPN	AF,Sw-Pow,45V,1A,5W,200MHz	14h$	Mat	BD135,BD226,BD375,2SD1378..
2SC1847	Si-NPN	AF,Sw-Pow,50V,1,5A,5W,150MHz	14h$	Mat	BD137,BD228,BD377,2SD794(A)..
2SC1848	Si-NPN	AF,Sw-Pow,70V,2A,10W,150MHz	13j$	Matsushita	(2SC1398,2SC2528,2SC3252)
2SC1849	Si-NPN	GenP,30V,0,1A,0,35W,150MHz	7e	Mat,Mic	BC168,BC183,BC238,BC548,2SD767..
2SC185	Si-NPN	=2SC184:250MHz	24b	Nec	BF240..241,BF254..255,BF594..595,..
2SC1850	Si-NPN	=2SC1849:60V	7e	-	BC174,BC182,BC190,BC546,2SD767..
2SC1851	Si-NPN	GenP,30V,0,5A,0,625W,200MHz	7e	Mat,Mic	BC337..338,BC635,BC637,2SC3377..
2SC1852	Si-NPN	=2SC1851:60V	7e	Mat	BC337A,BC637,BC639,2SD1226..
2SC1853	Si-NPN	HF-Pre/Mix//Osc.,30V,0,03A,230MHz	7c	Mat	BF240..241,BF254..255,BF594..595,..
2SC1854	Si-NPN	GenP,30V,0,05A,0,25W,150MHz	7c	Mat	BC168,BC183,BC238,BC548,2SC1890+
2SC1855	Si-NPN	TV-IF-AGC,20V,0,02A,550MHz	7f	Hit	BF198,BF225,BF310,BF367,BF596..
2SC1856	Si-NPN	VHF,AGC,20V,0,02A,550MHz	7f	Hit	BF225,BF310,BF314,BF502,BF505..
2SC1857	Si-NPN	Vid,300/300V,0,1A,0,8W,80MHz	2a$	Hit	BF259,BFR59,BFS89,2N5058,2SC3468+
2SC1858	Si-NPN	-		Hit	-
2SC1859(-1,-2)	Si-NPN	GenP,25V,1,5A,0,5W,140MHz	7c	Son	2SC2236,2SD773,2SD787..788,2SD1051
2SC186	Si-NPN	HF,20V,25mA,0,085W,200MHz,B=40	2a	Fui	BF240..241,BF254..255,BF594..595,..
2SC1860	Si-NPN	Sw,150/100V,2A,12,5W(Tc=25°)	2a$	Nec	BUX49..54,BUY41
2SC1861	Si-NPN	=2SC1860:300/250V	2a$	Nec	BUX52..54,BUY61..62
2SC1862	Si-NPN	=2SC1860:450/400V	2a$	Nec	BUX54,BUY61..62
2SC1863	Si-NPN	Sw,Pow,150/100V,7A,40W,<1000/3000nS	22a$	Nec	BUX60..61,MJE15030,2SC4329
2SC1864(A)	Si-NPN	=2SC1863:300V	22a$	Nec	TIP150,2SC2200,2SC3039,2SC4106..
2SC1865	Si-NPN	=2SC1863:450/400V	22a$	Nec	MJE13006,2SC2200,2SC3039,2SC4106..
2SC1866	Si-NPN	Sw,Pow,200/100V,7A,80W,<1000/3000nS	23a$	NEC	BUX18(A..C),TIP55A..58A,2SC3041..
2SC1867(A)	Si-NPN	=2SC1866:300/250(A=300/300)V	23a$	Nec	BUX18A..C,TIP55A..58A,2SC3041..
2SC1868	Si-NPN	=2SC1866:450/400V	23a$	Nec	BUX18C,TIP57A..58A,2SC3040..41..
2SC1869	Si-NPN	Sw,Pow,200/100V,10A,100W,<1000/3000nS	23a$	NEC	BUW24..26,BUX17(A..C),2SC3520..
2SC187	Si-NPN	=2SC186:a=50	2a	Fui	BF240..241,BF254..255,BF594..595,..
2SC1870	Si-NPN	=2SC1869:300/250V	23a$	Nec	BUW24..26,BUX17A..C,2SC3520..
2SC1871	Si-NPN	=2SC1869:450/400V,>10MHz	23a$	Nec	BUW24..26,BUX17C,2SC3520,2SC4140,..
2SC1871A	Si-NPN	=2SC1869:500/400V	23a$	-	BUW24..26,BUX17C,2SC3520,2SC4140,..
2SC1872	Si-NPN	Sw,Pow,150/100V,30A,200W,<1000/3000nS	68a$	Nec	2SC2128,2SC2940,2SC3224,2SD540..541..
2SC1873	Si-NPN	=2SC1872:300/250V	68a$	Nec	2SC1299,2SC1302,2SC1401,2SD643..
2SC1874	Si-NPN	=2SC1872:450/400V	68a$	Nec	2SC1300,2SC1470,2SC2250,2SD644..
2SC1875	Si-NPN	CTV-HD,(90°),1500/500V,3,5A,50W	23a$	NEC	BU208..209,BU706,2SD819,2SD850..
2SC1876(H)	Si-NPN-Darl	GenP,100V,0,5A,0,8W,B>2000	2a$	Hit	BSS52,2SD406,2SD688

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2SC1877..1878	Si-NPN	-		Hit	-
2SC1879	Si-N-Darl+Di	120V,2A,0.8W,B>1000	-		-
2SC1879(H)	Si-N-Darl+Di	GenP,120/120V,2A,0,8W,B>1000	2a$	Hit	2SD615
2SC188	Si-NPN	AF/HF/Sw,40V,0,5A,0,6W,150MHz	2a$	Fui	BC140..141,BC300..302,2N2218..19..
2SC1880(K)	Si-N-Darl+Di	=2SC1879:15W	17j$	Hit	BDW53D,BDW63D,2SD1147
2SC1881(K)	Si-N-Darl+Di	AF,Sw-Pow,60V,3A,30W,B>1000	17j$	Hit	BD71S,BDW23A,BDW53A,2SD837..
2SC1882(H)	Si-NPN-Darl	Sw,120/120V,5A,0,8W,B=5000	5t	Hit	2SC2165
2SC1883(K)	Si-NPN-Darl	AF,Sw-Pow,120/120V,5A,30W,B>1000	17j$	Hit	BD651,BDW63D,BDW73D,2SD1147..
2SC1884(H)	Si-NPN-Darl	AF,Sw-Pow,120/120V,8A,40W,B>1000	22a$	Hit	BD651,BDT63C,BDW73D,BDX33D..
2SC1885(NC)	Si-NPN	AF,LN,150V,0,05A,0,75W,200MHz	7c(9mm)	Mat	2SC2362K,2SC2631..2632,2SC3800
2SC1886	Si-NPN	UHF,30V,0,05A,1000MHz	7c	Hit	BF377..378,BF689K,BF763,2N2857..
2SC1887	Si-NPN	=2SC1886:1100MHz	7c	Hit	BF377..378,BF689K,BF763,2N2857..
2SC1888	Si-NPN	Hi-beta,80V,3A,0,8W,B=1000	2a$	Sak,Tos	(2SC1983,2SC3852,2SD1157,2SD1943,..)
2SC1889	Si-NPN	=2SC1888:100V	2a$	Sak,Tos	(2SD1259A,2SD1273A,2SD2092,2SD2156A)
2SC189	Si-NPN	AF/HF/Sw,60V,0,5A,0,6W,150MHz	2a$	Fui	BC140..141,BC300..302,2N2218..19..
2SC1890	Si-NPN	GenP,LN,90V,0,05A,0,3W,200MHz	7c	Hit	2SC2088..89,2SC2240,2SC2362,2SC2389..
2SC1890A	Si-NPN	=2SC1890:120V	7c	-	2SC2088,2SC2240,2SC2362,2SC2389..
2SC1891	Si-NPN	TV-HD,1200/400V,1,5A,50W,3MHz	23a$	Toshiba	BU204..206,BU705,2SC1922,2SD818..
2SC1892	Si-NPN	TV-HD,1500/500V,2,5A,50W,3MHz	23a$	Toshiba	BU205..206,BU705,2SC1922,2SD818..
2SC1893	Si-NPN	TV-HD,1500/500V,3,5A,50W,3MHz	23a$	Toshiba	BU208..209,BU706,2SD819,2SD850..
2SC1894	Si-NPN	TV-HD,1500/600V,5A,50W,3MHz	23a$	Toshiba	BU208(A),BU508A,2SC2928,2SD820..
2SC1895	Si-NPN	TV-HD,1500/600V,6A,50W,2MHz	23a$	Toshiba	BU508A,2SC3486,2SD649,2SD821..
2SC1896	Si-NPN	TV-HD,1500/600V,7A,50W,2MHz	23a$	Toshiba	BU508A,2SC3686,2SD822,2SD1016..
2SC1897	Si-NPN	GenP,30V,1A,0,6W,200MHz	7c	Njr	BC337..337,BC635,BC637,2SD1225..
2SC1898	Si-NPN	HF/AF,30V,0,03A,500MHz	7f	Njr	BF198..199,BF224..225,BF596..597,..
2SC1899	Si-NPN	HF/AF,30V,0,02A,500MHz	7f	Njr	BF198..199,BF224..225,BF596..597,..
2SC19	Si-NPN	AF,Sw,40V,0,4A,0,6W,>70MHz	2a$	Tos	BC140..141,BC300..302,2N3053..
2SC190	Si-NPN	AF/HF/Sw,60V,0,5A,0,6W,180MHz	2a$	Fui	BC140..141,BC300..302,2N2218..19..
2SC1900	Si-NPN	Mix,120/120V,0,05A,0,3W,90MHz	7c	Njr	BF297..299,BSS38,2SC2240,2SD756..
2SC1901	Si-NPN	UHF,25V,0,02A,0,6W,1,4GHz	2a$	Fui	(BFR37,BFW30,BFX73,BFX89,..)
2SC1902	Si-NPN	VHF/UHF,40V,0,3A,0,6W,650MHz	2a$	Fui	BFX55,2SC1199,2SC1252,2SC1365..66
2SC1903	Si-NPN	Vid-Pow,150/120V,0,05A,130MHz	14h$	Fui	BF415,BF457,BF469,2SD1609..
2SC1904	Si-NPN	=2SC1903:150/150V	14h$	Fui	BF415,BF457,BF469,2SD1609..
2SC1905(H)	Si-NPN	Vid-Pow,TV-HD,350/300V,0,2A,15W	17j$	Mat	(2SC1929,2SC4714)
2SC1906	Si-NPN	VHF-Mix/Osc,30V,50mA,1000MHz	7c	Hit	BF377..378,BF689K,BF763,2N2857..
2SC1907	Si-NPN	TV-Tuner,UHF-Osc,30V,50mA,1100MHz	7c	Hit	BF377..378,BF689K,BF763,2N2857..
2SC1908	Si-NPN	VHF/Sw,30V,0,03A,200MHz	7c	Son	BF240..241,BF254..255,BF594..595,..
2SC1909	Si-NPN	AM-Pow,75V,3A,Pq=5,5W(27MHz)	17j$	Nec	2SC1306,2SC1816,2SC2092
2SC191	Si-NPN	HF,60V,0,01A,0,25W,50MHz	2a	Son	(BF240..241,BF254..255,BF594..595,..)
2SC1910	Si-NPN	Dual,UHF,15V,0,08A,0,4W,7GHz	-	Tos	-
2SC1911	Si-NPN	Dual,UHF,20V,0,03A,0,3W,6,5GHz	-	Tos	-
2SC1912	Si-NPN	Dual,UHF,20V,0,03A,0,3W,6,5GHz	-	Tos	-
2SC1913	Si-NPN	AF,Sw-Pow,150/150V,1A,15W,120MHz	17j$	Mat	2SC2238(A),2SC2344,2SC2592,2SD608(A)
2SC1913A	Si-NPN	=2SC1913:180/180V	17j$	-	2SC2238A,B,2SC2344,2SC2592,2SD608A
2SC1914	Si-NPN	AF/Vid,90/90V,0,05A,0,2W,150MHz	7b	Mit	2SC1890(A),2SC2240,2SC2363,2SD756..
2SC1914A	Si-NPN	=2SC1914:120/120V	7b	-	2SC1890A,2SC2240,2SC2363,2SD756(A),..
2SC1915	Si-NPN	Vid,120/120V,0,05A,0,8W,200MHz	7b	Mit	BSS38,2SC1890A,2SC2240,2SC2363..
2SC1916	Si-NPN	GenP,LN,50V,0,1A,0,2W,150MHz	7b	Mit	BC184,BC414,BC550,2SC2240..
2SC1917	Si-NPN	=2SC1916:35V	7b	Mit	BC169,BC184,BC239,BC549,2SC2390+
2SC1918	Si-NPN	GenP,35V,0,1A,0,2W,150MHz	7b	Mit	BC168,BC183,BC238,BC548,2SD767..
2SC1919	Si-NPN	GenP,LN,50V,0,03A,0,2W,150MHz	7b	Mit	BC184,BC414,BC550,2SC2240..
2SC192	Si-NPN	=2SC191:10MHz	2a	Son	(BF240..241,BF254..255,BF594..595,..)
2SC1920	Si-NPN	Dual,UHF,15V,0,08A,0,4W,7GHz	-	Tos	-
2SC1921	Si-NPN	Vid,250/200V,0,05A,0,6W,130MHz	7c(9mm)	Hit	BF298..299,BF422(A),2SC3468..
2SC1922	Si-NPN	TV-HD,1500/800V,2,5A,50W,5MHz	23a$	Hitachi	BU205..206,BU705,2SC3483,2SD818..
2SC1923	Si-NPN	FM-Preamp/Mix/IF,550MHz	7c	Tos,Mic	BF241,BF255,BF314,BF502,BF505..
2SC1924	Si-NPN	Dual,UHF,20V,0,05A,3GHz	-	Nec	-
2SC1925	Si-NPN	Dual,UHF,20V,0,05A,3GHz	-	Nec	-
2SC1926	Si-NPN	Dual,UHF,30V,0,05A,2GHz	-	Nec	-
2SC1927	Si-NPN	Dual,UHF,30V,0,05A,2GHz	-	Nec	-
2SC1928	Si-NPN	GenP,50V,0,05A,0,315W,140MHz	10b	Son	BC167,BC182,BC237,BC547,2SC1890+
2SC1929	Si-NPN	AF,Sw-Vid-Pow,300/300V,0,4A,25W,80MHz	17j$	Mat	BUW40(A,B),2SC1263(A),2SC2022..
2SC193	Si-NPN	=2SC191:30MHz	2a	Son	(BF240..241,BF254..255,BF594..595,..)
2SC1930(A,F,AF)	Si-NPN	UHF,16V,0,03A,0,15W,8GHz	51r	Fui	2SC1655..56,2SC3276,2SC3586..87

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2SC1931(F)	Si-NPN	Dual, UHF, 16V, 0,03A, 0,3W, 8GHz	-	Fui	-
2SC1932(F)	Si-NPN	Dual, UHF, 16V, 0,03A, 0,4W, 8GHz	-	Fui	-
2SC1933(F)	Si-NPN	Dual, UHF, 15V, 0,04A, 0,4W, 6GHz	-	Fui	-
2SC1934(F)	Si-NPN	Dual, UHF, 20V, 0,08A, 1W, 6GHz	-	Fui	-
2SC1935(F)	Si-NPN	UHF, 15V, 0,03A, 0,25W, 6GHz	51r	Fui	BFQ57..58, BFQ74
2SC1936(F)	Si-NPN	Dual, UHF, 15V, 0,03A, 0,3W, 6GHz	-	Fui	-
2SC1937(F)	Si-NPN	UHF, 15V, 0,07A, 0,3W, 6GHz	51r	Fui	BFQ82, 2SC2876
2SC1938(F)	Si-NPN	Dual, UHF, 15V, 0,03A, 0,4W, 6GHz	-	Fui	-
2SC1939(F)	Si-NPN	Dual, UHF, 15V, 0,03A, 0,4W, 6GHz	-	Fui	-
2SC194	Si-NPN	=2SC191	2a	Son	(BF240..241, BF254..255, BF594..595,..)
2SC1940	Si-NPN	AF, 120/120V, 0,05A, 1W, 120MHz	9b	NEC	2SC2362..63, 2SC2631..32, 2SD2030..
2SC1941	Si-NPN	=2SC1940: 160/160V	9b	Nec	2SC2631..32, 2SC3248, 2SD2030..31
2SC1942	Si-NPN	TV-HD, 1500/800V, 3A, 50W, 5MHz	23a$	Hitachi	BU208..209, BU705(A), 2SD819, 2SD850..
2SC1943	Si-NPN	UHF-Dr/Out, 35V, 0,4A, Pq=0,4W(470MHz)	51r	Mit	BLU98, MRF627..628, 2N6256, 2SC3019
2SC1944	Si-NPN	AM-Pow, 80V, 6A, Pq=16W(27MHz)	17j$	Mit	2SC1817, 2SC1969, 2SC2050, 2SC2098
2SC1945	Si-NPN	=2SC1944:	17k*	Mit	2SC3133
2SC1946	Si-NPN	VHF-Pow, 35V, 7A, Pq=32W(175MHz)	58s*	Mit	-
2SC1946A	Si-NPN	=2SC1946: Pq=35W(175MHz)	58s*	-	-
2SC1947	Si-NPN	VHF-Dr/Out, 35V, 1A, Pq=4W(175MHz)	2a*	Mit	BFS22, BFW46, MRF237, 2N3924
2SC1948	Si-NPN	UHF-A, 15V, 0,02A, 0,15W, 8GHz	52s*	Nec	BFQ77, 2SC1655..56, 2SC1923, 2SC3276
2SC1949	Si-NPN	UHF-A, 30V, 0,13A, 0,58W, 2,7GHz	51s	Nec	BFG34, BFG96
2SC195	Si-NPN	=2SC191: 30V, 10MHz	2a	Son	BF240..241, BF254..255, BF594..595,..
2SC1950	Si-NPN	UHF-Dr/Out, 28V, 0,2A, 5W, 4GHz	-	Nec	2SC2093
2SC1951	Si-NPN	Vid, 120/120V, 0,1A, 0,75W, 140MHz	7c(9mm)	Son	BSS38, 2SC2240, 2SC2459, 2SC3245(A)..
2SC1952	Si-NPN	UHF-A/Dr, 45V, 0,3A, 0,8W, 2GHz	2a	Nec	2SC1253, 2SC1366
2SC1953	Si-NPN	AF, 150/150V, 0,05A, 200MHz	14h$	Mat	BF415, BF457, BF469, 2SD1609..
2SC1954	Si-NPN	UHF-A, AGC, 25V, 0,15A, 0,45W, 1,5GHz	7c	Fui	2SC2408, 2SC4693
2SC1955	Si-NPN	VHF-Dr/Out, 35V, 0,8A, Pq=3,2W(175MHz)	2a*	Tos	BFS22, BFW46, MRF237, 2N3924
2SC1956	Si-NPN	VHF-Pow, 35V, 3,5A, Pq=17W(175MHz)	55r	Tos	BLY89, MRF209, 2N5591, 2N6082
2SC1957	Si-NPN	AM-Out, 75V, 1A, Pq=1,8W(27MHz)	14h$	Nec	2SSC2091, 2SC2314
2SC1958	Si-NPN	-		Nec	-
2SC1959	Si-NPN	GenP, 35V, 0,5A, 0,5W, 300MHz	7c	Tos	BC337..338, BC635, BC637, 2SC3377..
2SC196	Si-NPN	=2SC191: 30V, 30MHz	2a	Son	BF240..241, BF254..255, BF594..595,..
2SC1960	Si-NPN	Fast-Sw, 20V, 0,2A, 0,3W, -/15nS	7a	Fui	BSS11..12, BSY17..18, 2N2368..69(A),..
2SC1961	Si-NPN	FM, 35V, 25mA	7f	Son	BF240..241, BF254..255, BF594..595,..
2SC1962	Si-NPN	AF, Sw-Vid-Out, 200/200V, 0,5A, 45MHz	13g$	Sony	BF381..382, BF460..462, MPSU10
2SC1963	Si-NPN	Dual, 25V, 0,2A, 0,27W, 140MHz	6-DIP/bg1	Son	-
2SC1964	Si-NPN	AM-Pow, 80V, 3,5A, Pq=3,4W(27MHz)	17j$	Mit	2SC1678..79, 2SC2075, 2SC2078
2SC1965(A)	Si-NPN	VHF-Pow, 35..40V, 1..2A, Pq=6,5W(175MHz)	43a*	Mit	-
2SC1966	Si-NPN	UHF-Pow, 35V, 1A, Pq=3,5W(470MHz)	58s*	Mit	2SC3020
2SC1967	Si-NPN	UHF-Pow, 35V, 2A, Pq=8W(470MHz)	58s*	Mit	2SC2992, 2SC3021
2SC1968	Si-NPN	35V, 5A, 3W, 470MHz	-		-
2SC1968(A)	Si-NPN	UHF-Pow, 35V, 5A, Pq=16W(470MHz)	58s*	Mit	2SC3022
2SC1969	Si-NPN	AM-Pow, 60V, 6A, Pq=16W(27MHz)	17j$	Mit	2SC1944, 2SC2050, 2SC2098
2SC197	Si-NPN	=2SC191: 30V	2a	Son	BF240..241, BF254..255, BF594..595,..
2SC1970	Si-NPN	VHF-Dr/Out, 40V, 0,6A, Pq=1,3W(175MHz)	17j$	Mit	-
2SC1971	Si-NPN	VHF-Pow, 35V, 2A, Pq=7W(175MHz)	17k*	Mit	-
2SC1972	Si-NPN	VHF-Pow, 35V, 3,5A, Pq=15W(175MHz)	17k*	Mit	-
2SC1973	Si-NPN	HF-Osc/Dr, 50V, 0,5A, Pq=1W(50MHz)	7c(9mm)	Mat	(MRF229..239)
2SC1974	Si-NPN	HF-Pow, 80V, 2A, Pq=5W(50MHz)	17j$	Mat	-
2SC1975	Si-NPN	HF-Pow, 120V, 2A, Pq=3,8W(50MHz)	17j$	Mat	-
2SC1976	Si-NPN	VHF-Out, 36V, 0,5A(ss), Pq>0,6W(175MHz)	7c(9mm)	Mat	(BRF98, MRF207, MRF225, MRF607)
2SC1977	Si-NPN	VHF-Pow, 36V, 1A(ss), Pq>2W(175MHz)	14h$	Mat	-
2SC1978	Si-NPN	VHF-Pow, 36V, 1,5A(ss), Pq>7W(175MHz)	17f$	Mat	-
2SC198(A)	Si-NPN	VHF-A/Dr, 50V, 0,5A, 0,8W, 350MHz	5g	Fui	BFS23, BFX55, BLY34, 2SC2852
2SC1980	Si-NPN	GenP, LN, 120V, 0,02A, 0,25W, 200MHz	7c	Mat	2SC2088, 2SC2240, 2SC2362, 2SC2389
2SC1981	Si-NPN	Hi-beta, Hi-Ueb, 50V, 0,1A, 0,3W, 30MHz	2a$	Son	2SC3069, 2SC3615, 2SC3820, 2SC3836
2SC1982(S)	Si-NPN	AF/HF/Sw, 140/140V, 1A, 0,625W, 120MHz	2a$	Son	BSS43, BSW68, 2N3019..20, 2SC1860
2SC1983	Si-NPN	Hi-beta, 80V, 3A, 30W, B=700	17j$	Sak	2SD1157, 2SD1943
2SC1984	Si-NPN	=2SC1983: 100V	17j$	Sak	2SC2316, 2SC2491
2SC1985	Si-NPN	AF, Sw-Pow, 80V, 6A, 40W, 10MHz	17j$	Sak	BD243B, BD543B, BD809, 2SC3254..
2SC1986	Si-NPN	=2SC1985: 100V	17j$	SAk	BD243C, BD543C, BD801, 2SD613..
2SC1987	Si-NPN	TV-HD, Sw, Pow, 300/90V, 6A, 50W, 12MHz	22a$	Hit	BU406..408, 2SD884..885, 2SD1163..
2SC1988	Si-NPN	UHF, LN, 25V, 0,07A, 0,35W, 4,5GHz	5g	Nec	BFQ63, 2SC2570, 2SC3037

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2SC1989	Si-NPN	HF/AF,30V,0,03A,300MHz	7c	Mat	BF240..241,BF254..255,BFS94..595,..
2SC199	Si-NPN	HF/Sw,80V,0,05A,0,6W,130MHz	2a$	Tos	(BC140..141,BC300..301,BSW39)
2SC1990	Si-NPN	HF/AF,30V,15mA,650MHz	7c	Mat	BF198..199,BF224..225,BFS96..597,..
2SC1991	Si-NPN	GenP,60V,0,1A,0,625W,250MHz	7e	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC1992	Si-NPN	GenP,50V,0,1A,0,3W,300MHz	7a	Nec	BC167,BC182,BC237,BC547,2SD767..
2SC1993	Si-NPN	GenP,30V,0,1A,0,3W,300MHz	7a	Nec	BC168,BC183,BC238,BC548,2SD767..
2SC1994	Si-NPN	GenP,LN,45V,0,1A,0,3W,300MHz	7a	Nec	BC184,BC413..414,BC550,2SC2240..
2SC1995	Si-NPN	=2SC1994:50V	7a	Nec	BC414,BC550,2SC2240,2SC2390..
2SC1996	Si-NPN	GenP,50V,0,8A,0,625,100MHz	7a	Nec	BC337,BC637,BC639,2SD667,2SD1226+
2SC1997	Si-NPN	=2SC1997:30V	7a	Nec	BC337..338,BC635,BC637,2SD1225..
2SC1998	Si-NPN	GenP,80V,0,1A,0,5W,300MHz	7a	Nec	BC546,2SC2240,2SC2459,2SC3245(A)..
2SC1999	Si-NPN	=2SC1998:50V	7a	Nec	BC167,BC182,BC237,BC547,2SD767..
2SC20	Si-NPN	AF,Sw,40V,0,4A,0,6W,90MHz	2a$	Tos	BC140..141,BC300..302,2N3053..
2SC200	Si-NPN	VHF-A/Dr,40V,0,3A,0,65W,350MHz	2a$	Fui	BFS23,BFX55,BLY34,2SC2852
2SC2000	Si-NPN	GenP,60V,0,2A,0,6W,70MHz	7c	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC2001	Si-NPN	GenP,30V,0,7A,0,6W,170MHz	7c	Nec	BC337..338,BC635,BC637,2SD1225..
2SC2002	Si-NPN	GenP,60V,0,3A,0,6W,140MHz	7c	Nec	BC337A,2SC1627,2SC3939,2SC4414..
2SC2003	Si-NPN	=2SC2002:80V	7c	Nec	BC639,2SC1627,2SC3939,2SC4414..
2SC2004..2007	Si-NPN	-		Nec	-
2SC2008	Si-NPN	HF,35V,0,1A,560MHz	7a	Son	BF370,BF920..921S,BF959..
2SC2009	Si-NPN	VHF/IF,35V,0,1A,550MHz	7f	Son	BF370,BF920..921S,BF959..
2SC201	Si-NPN	=2SC200:20V	2a$	Fui	BFS23,BFX55,BLY34,2SC2852
2SC2010	Si-NPN	HF,35V,0,03A,400MHz	7f	Son	BF198..199,BF224..225,BF596..597,..
2SC2011	Si-NPN	VHF/IF,30V,0,05A,630MHz	7f	Son	BF198,BF225,BF310,BF314,BF505..
2SC2012	Si-NPN	HF,30V,0,03A,0,5W,200MHz	7c	Son	BF240..241,BF254..255,BFS94..595,..
2SC2013	Si-NPN	VHF,LN,35V,25mA,700MHz	7f	Son	BF225,BF314,BF502,BF505,BF507..
2SC2014	Si-NPN	GenP,100V,0,2A,0,5W,100MHz	7c	Son	2SC2240,2SC2459,2SC2345(A),2SC3248
2SC2015..2016	Si-NPN	-		Son	-
2SC2017	Si-NPN	Sw,Pow,450/400V,10A,100W,>10MHz	23a$	Mitsubishi	BUW24..26,BUW72,BUX14,2SC3520..
2SC2018	Si-NPN	Sw,Pow,300/300V,15A,100W,>10MHz	23a$	Mitsubishi	BUX13,BUY50,MJ15024,2SC2307..
2SC2019	Si-NPN	Sw,Pow,200/200V,15A,100W,>10MHz	23a$	Mitsubishi	BUX41,2SC2944,2SD552,2SD583..
2SC202	Si-NPN	=2SC200:80V	2a$	Fui	-
2SC2020	Si-NPN	AM-Pow,45V,2A,Pq=7W(27MHz)	17j$	Son	2SC1816,2SC2029,2SC2043
2SC2021(M,LN)	Si-NPN	=2SC1740(LN):	9c	Rhm	→2SC1740(LN)
2SC2022	Si-NPN	Sw,Pow,300/300V,1A,30W,10MHz	17j$	Sak	TIP47..50,2SC2023,2SD860(A,B)..
2SC2023	Si-NPN	Sw,Pow,300/300V,2A,40W,10MHz	17j$	Sak	TIP75(A..C),2SC2738,2SC3055..
2SC2024	Si-NPN	Relay-Dr,80V,1A,150MHz	14h$	Fui	BD139,BD230,BD379,2SD1177..1178
2SC2025	Si-NPN	UHF,LN,35V,0,05A,0,35W,2,2GHz	5g	Nec	BFR37,BFS55,BFW30,BFX73
2SC2026	Si-NPN	UHF,30V,0,05A,0,25W,2,2GHz	7f	Nec	BF357,2SC2570(A),2SC3037,2SC3777
2SC2027	Si-NPN	TV-HD,1500/800V,5A,50W,8MHz	23a$	Hitachi	BU208A,BU508A,2SC2928,2SD820..
2SC2028	Si-NPN	AM-Pow,80V,1,5A,Pq=0,7W(27MHz)	14h$	Fui	2SC1957,2SC2091,2SC2314
2SC2029	Si-NPN	AM-Pow,80V,2A,Pq=6W(27MHz)	17j$	Fui	2SC1816,2SC2020
2SC203	Si-NPN	HF/Sw,40V,0,2A,0,35W,350MHz	2a$	Fui	BSW41,BSY63,2N708,2N914,2N4123..
2SC2030	Si-NPN	-		Fui	-
2SC2031	Si-NPN	UHF-Dr/Out,45V,0,5A,Pq=2,5W(470MHz)	55r	Fui	BLW90,BLX92,2SC2892
2SC2032	Si-NPN	UHF-Pow,45V,1A,Pq=5,5W(470MHz)	55r	Fui	BLW93,BLX93,2SC1040,2SC2700
2SC2033	Si-NPN	UHF-Pow,45V,3A,Pq=18W(470MHz)	55r	Fui	BLW94,BLX94,2SC2894
2SC2034	Si-NPN	HF-Dr/Out,120V,2A,Pq=3,8W(50MHz)	2a$	Mat	-
2SC2035	Si-NPN	GenP,50V,0,3A,0,3W,350MHz	7a	Fui	2SC2053,(BC337,2SC1627,2SC2002..03)
2SC2036	Si-NPN	AM-Dr/Out,80V,1A,Pq=1..4W	14h$	Tos	-
2SC2037	Si-NPN	UHF,30V,0,05A,0,25W,2GHz	7e	Nec	BF357,2SC2570(A),2SC3037,2SC3777
2SC2038	Si-NPN	HF-Pow,70V,5A,75W,200MHz	-	Mit	-
2SC2039	Si-NPN	AM-Pow,70V,8A,Pq=50W(30MHz)	?57s	Mit	-
2SC204(F)	Si-NPN	=2SC203:30V,250MHz	2a$	Fui	BSW41,BSY63,2N708,2N914,2N4123..
2SC2040	Si-NPN	VHF-Dr/Out,40V,0,5A,5W,1,8GHz	55r	Mit	-
2SC2041..2042	Si-NPN	-		Fui	-
2SC2043	Si-NPN	AM-Pow,70V,4A,Pq=16W(27MHz)	17j$	Fui	2SC1817,2SC1944,2SC1969,2SC2098
2SC2044	Si-NPN	UHF-Pow,55V,6A,Pq=42W(770MHz)	?57s	Fui	-
2SC2045	Si-NPN	-		Fui	-
2SC2046..2049	Si-NPN	-		Nec	-
2SC205	Si-NPN	=2SC203:80V	2a$	Fui	BSW63..64,2N2221A..2222A
2SC2050	Si-NPN	AM-Pow,60V,6A,Pq>13W(50MHz)	17j$	Mat	2SC1307
2SC2051	Si-NPN	GenP,60V,0,25A,0,5W,300MHz	7c	Fui	BC337A,2SC1627,2SC2002..03,2SC4414..
2SC2053	Si-NPN	VHF-Osc/Dr,40V,0,3A,Pq=0,2W(175MHz)	7b	Mit	2SC2851

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2SC2054	Si-NPN	-		Mit	-
2SC2055	Si-NPN	VHF-Dr/Out,18V,0,3A,Pq=0,25W(175MHz)	7b	Mit	2SC2851
2SC2056	Si-NPN	VHF-Dr/Out,18V,0,6A,Pq=2W(175MHz)	2a*	Mit	BFQ42,BFS22,BLY33,MRF237,2SC2852
2SC2057	Si-NPN	VHF/IF,30V,0,02A,500MHz	7d	Sanyo	BF198,BF225,BF310,BF314,BFS02..
2SC2058	Si-NPN	40V,0.05A,0.25W	-		-
2SC2058(S)	Si-NPN	HF,40V,0,05A,0,25W,300MHz	7c,41c	Rhm	BF240..241,BF254..255,BFS94..S95,..
2SC2059	Si-NPN	FM,25V,0,02A,500MHz	?35d	Rhm	-
2SC2059-JM	Si-NPN	-	ч35	Rhm	→2SC2059
2SC2059-JN	Si-NPN	-	ч35	Rhm	→2SC2059
2SC2059-JP	Si-NPN	-	ч35	Rhm	→2SC2059
2SC2059K	Si-NPN	=2SC2059:	35a	-	BF599,BF799,2SC3015,2SC3374
2SC2059K-M	Si-NPN	-	35	Rhm	→2SC2059K
2SC2059K-N	Si-NPN	-	35	Rhm	→2SC2059K
2SC2059K-P	Si-NPN	-	35	Rhm	→2SC2059K
2SC206	Si-NPN	VHF,20V,25mA,0,2W,200MHz	5g	Fui	BF225,BF310,BF314,BFS02,BF505..
2SC2060	Si-NPN	GenP,40V,1A,0,75W,150MHz	7c(9mm)	Rhm	2SD667,2SD863,2SD1331,2SD1207..
2SC2061	Si-NPN	GenP,80V,0,7A,0,75W,120MHz	7c(9mm)	Rhm	2SC3228,2SD667,2SD1292,2SD1812..
2SC2062(S)	Si-NPN-Darl	GenP,40V,0,3A,0,3W,200MHz,B>5000	7c	Rhm	BCS17,BC617,BC875,MPSA25..29..
2SC2063(M)	Si-NPN	=2SC2058:	9c	Rhm	→2SC2058
2SC2064	Si-NPN	-		Fui	-
2SC2065	Si-NPN	UHF-Dr/Out,35V,0,25A,6W,3,2GHz	55s	Nec	BFQ68
2SC2066	Si-NPN	UHF-Dr/Out,35V,0,45A,7W,2GHz	55s	Nec	BFT99
2SC2067	Si-NPN	GenP,35V,1A,0,5W,150MHz	7c	Fui	BC337..338,BC635,BC637,2SD1225..
2SC2068	Si-NPN	CTV-Chroma-Out,300V,0,05A,95MHz	13j$	Toshiba	(BF461..462,BF758..759,MPSU10,..)
2SC2069	Si-NPN	Sw,20V,0,3A,0,35W,-/100nS	2a$	Fui	BSW41,BSX87..88,BSY62..63,2N706A..
2SC207	Si-NPN	=2SC206:800MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC2070	Si-NPN	Sw,40V,0,3A,0,3W,<160/172nS	2a$	Fui	BSW41,BSX87..88,BSY63,2N914..
2SC2071	Si-NPN	Vid,250/220V,0,05A,130MHz	14h$	Fui	BF415,BF457,BF469,2SC4147..
2SC2072	Opto	-		Son	-
2SC2073	Si-NPN	TV-VD,AF,Sw,Pow,150V,1,5A,25W,4MHz	17j$	Tos	BD239D,2SC1669,2SD608(A),2SD1138..
2SC2073A	Si-NPN	=2SC2073:Iso	17c	-	2SC3298(A,B),2SC3364,2SC3567,2SC4159
2SC2074	Si-NPN	-		Tos	-
2SC2075	Si-NPN	AM-Pow,80V,4A,Pq>3,5W(27MHz)	17j$	Tos	2SC1306,2SC1816,2SC1909,2SC2092
2SC2076	Si-NPN	FM,35V,0,02A,150MHz	7c	Mat	BF240..241,BF254..255,BF594..595,..
2SC2077	Si-NPN	-		Mat	-
2SC2078	Si-NPN	AM-Pow,80V,3A,Pq>4W(27MHz)	17j$	Sanyo	2SC1306,2SC1816,2SC1909,2SC2092
2SC2079	Si-NPN	GenP,100V,0,7A,1W,100MHz	7co	Sanyo	BC639,2SC2235,2SD667,2SD1292..
2SC208	Si-NPN	=2SC206:550MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC2080	Si-NPN	AF,Sw-Pow,60V,1A,35/105nS	14h$	Fui	BD137,BD228,BD377,2SD1378..
2SC2081	Si-NPN	UHF-Dr/Out,38V,0,75A,Pq>2,8W(500MHz)	55s	Nec	BLW43,BLW80,2N5945
2SC2082	Si-NPN	UHF-Pow,38V,2,2A,Pq>7,9W(500MHz)	55s	Nec	BLW44,2N5946
2SC2083	Si-NPN	UHF-Pow,38V,3A,Pq=14W(500MHz)	55s	Nec	BLW15,BLX69,2SC1338
2SC2084	Si-NPN	-		Nec	-
2SC2085	Si-NPN	AF,Sw,Vid-Pow,300V,0,1A,10W,55MHz	17j$	Mat	2SC1505..1507,2SC1755..1757,2SC1905
2SC2086	Si-NPN	AM-Osc/Dr,75V,1A,Pq=0,45W(27MHz)	7b	Mit	-
2SC2087	Si-NPN	Vid,300V,5mA,0,1W,80MHz	2a$	Oki	BF299,BF420,BF483,2SC4218..
2SC2088	Si-NPN	GenP,LN,120V,0,05A,0,3W,150MHz	7c	Tos	2SC1775A,2SC1845,2SC2240,2SC2459..
2SC2089	Si-NPN	GenP,LN,120V,0,05A,0,3W,150MHz	7c	Tos	2SC1775A,2SC1845,2SC2240,2SC2459..
2SC209	Si-NPN	=2SC206:450MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC2090	Si-NPN	-		Nec	-
2SC2091	Si-NPN	AM-Pow,75V,1A,Pq=1,8W(27MHz)	14h$	Hit	2SC1957,2SC2314
2SC2092	Si-NPN	AM-Pow,75V,3A,Pq=5W(27MHz)	17j$	Hit	2SC1306,2SC1816,2SC1909
2SC2093	Si-NPN	UHF-A/Dr/Out,28V,0,2A,Pq=0,25W(5GHz)	-	Nec	2SC1950
2SC2094	Si-NPN	VHF/UHF-Pow,40V,3,5A,Pq>17,5W(175MHz)	58s*	Mit	-
2SC2095..2096	Si-NPN	-		Mit	-
2SC2097	Si-NPN	AM-Pow,50V,15A,Pq=85W(30MHz)	?57s*	Mit	-
2SC2098	Si-NPN	AM-Pow,70V,6A,Pq=15W(28MHz)	17j$	Tos	2SC1944,2SC1969,2SC2050,2SC1817
2SC2099	Si-NPN	AM-Pow,40V,6A,Pep=20W(28MHz)	59r	Tos	-
2SC21	Si-NPN	AF/HF/Sw-Pow,60V,2A,60W,6MHz	23a$	Tos	BD245A,BD311,BD313,2N4914..15..
2SC210	Si-NPN	HF/Sw,50V,0,5A,0,65W,150MHz	2a$	Fui	BC140..141,BC300..302,2N3053..
2SC2100	Si-NPN	AM-Pow,40V,15A,Pep=60W(28MHz)	59r	Tos	MRF421,2SC2290
2SC2101	Si-NPN	VHF-Pow,35V,2A,Pq>6W(175MHz)	55r	Tos	BLW19,MRF208,MRF212,2N5590
2SC2102	Si-NPN	VHF-Pow,35V,3,5A,Pq>15W(175MHz)	55r	Tos	BLY89,MRF209,2N5591,2N6082
2SC2103(A)	Si-NPN	VHF-Pow,40V,6A,Pq>24W(175MHz)	55r	Tos	BLW20,BLW31,2N6084

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2SC2104	Si-NPN	UHF-Dr/Out,35V,0,8A,Pq>3W(470MHz)	55r	Tos	2N5945
2SC2105	Si-NPN	UHF-Pow,35V,1,4A,Pq>6W(470MHz)	55r	Tos	BLW14,BLW44,2N5946
2SC2106	Si-NPN	UHF-Pow,35V,2,8A,Pq>12W(470MHz)	55r	Tos	BLW15,BLX69,2SC1338
2SC2107	Si-NPN	60V,0,1A,300MHz	35a	Nec	BC846,BCV71..72,BSR17,2SC3361
2SC2107-G3	Si-NPN	-	35	Nec	→2SC2107
2SC2107-G4	Si-NPN	-	35	Nec	→2SC2107
2SC2107-G5	Si-NPN	-	35	Nec	→2SC2107
2SC2107-G6	Si-NPN	-	35	Nec	→2SC2107
2SC2108	Si-NPN	HF/Sw,120V,0,7A,0,8W,250MHz	2a$	Nec	2N2102,2N2405,2SC959
2SC2109	Si-NPN	GenP,60V,0,2A,0,3W,300MHz,45/400nS	7a	Nec	BC174,BC182,BC546,2N3903..04..
2SC211	Si-NPN	=2SC210:25V	2a$	Fui	BC140..141,BC300..302,2N3053..
2SC2110	Si-NPN	-		Fui	-
2SC2111	Si-NPN	Sw,40V,0,2A,0,3W,500MHz,<20/40nS	7a	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC2112	Si-NPN	-		Nec	-
2SC2113	Si-NPN	AF/HF/Sw-Pow,40V,1A,4W,100MHz	14h$	Mat	BD135,BD226,BD375,2SC3419..
2SC2114	Si-NPN	UHF-A,15V,0,08A,0,225W,7GHz	24f	Tos	2SC2876,2SC3062
2SC2115	Si-NPN	UHF-A,20V,0,03A,0,15W,6,5GHz	24f	Tos	BFQ57..58,BFQ74,2SC1655..1656...
2SC2116	Si-NPN	UHF-A,30V,0,05A,0,225W,3GHz	24f	Tos	BFQ72,BFT65
2SC2117	Si-NPN	VHF-Dr/Out,35V,0,8A,Pq=3,2W(175MHz)	43a*	Tos	-
2SC2118	Si-NPN	VHF-Pow,35V,1,4A,Pq=6W(175MHz)	43a*	Tos	-
2SC2119	Si-NPN	AM-Pow,80V,4A,Pq>6W(28MHz)	17j$	Tos	2SC1816,2SC2043
2SC212	Si-NPN	=2SC210:80V	2a$	Fui	BC140..141,BC300..301,2N1990..
2SC2120	Si-NPN	GenP,30V,0,8A,0,6W,120MHz	7c	Tos,Mic	BC337..338,BC635,BC637,2SD1225..
2SC2121	Si-NPN	Sw,Pow,750/300V,3A,50W,8MHz	23a$	Tos	BU126,BU326(A),BU426(A),2SD1183
2SC2122	Si-NPN	TV-HD,800/325V,10A,50W,6MHz	23a$	Toshiba	BU626A,2SC2123,2SD1094,2SD1279
2SC2122A	Si-NPN	=2SC2122:1000/400V	23a$	-	BU626A,2SC2123,2SD1094,2SD1279
2SC2123	Si-NPN	TV-HD,1000/400V,12A,50W,6MHz	23a$	Toshiba	2SC3644,(BU626A,2SD1094,2SD1279)
2SC2124	Si-NPN	TV-HD,2200/800V,2A,5W(Tc=90°)	23a$	Toshiba	BU225,BUY71,2SD621,2SD838
2SC2125	Si-NPN	TV-HD,2200/800V,5A,50W,5MHz	23a$	Toshiba	-
2SC2126(A)	Si-NPN	Sw,Pow,200/200V,3A,30W,<1/2,5µS	22a$	Shi	TIP75(A..C),2SD422..423
2SC2127(A)	Si-NPN	Sw,Pow,200/200V,10A,100W,<1/3µS	23a$	Shidengen	BUX17(A..C),BUY18,TIP160..162..
2SC2128(A)	Si-NPN	Sw,Pow,200/200V,30A,200W,<1/3µS	68a$	Shi	2SC1301,2SC2249,2SC2445,2SC2940..
2SC2129	Si-NPN	=2SC2130:ra	7b	Mit	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2SC213	Si-NPN	=2SC210:1,5W	2a$	Fui	(BD137,BD228,2SD1200,2SD1378,..)
2SC2130	Si-NPN	GenP,70V,0,1A,0,2W,100MHz	7b	Mit	BC174,BC190,BC546,2SD2030..31..
2SC2131	Si-NPN	UHF-Dr/Out,40V,0,6A,Pq=1,6W(500MHz)	2a*	Mit	BLX65,MRF629,2SC2762,2SC3185
2SC2132	Si-NPN	UHF-Pow,35V,9A,Pq=30W(470MHz)	?57s*	Mit	BLU45/12,MRF648
2SC2133	Si-NPN	VHF-Pow,55V,5A,Pq=34W(220MHz)	?57s*	Mit	-
2SC2134	Si-NPN	UHF-Pow,55V,10A,Pq=70W(220MHz)	?57s*	Mit	MRF327
2SC2135	Si-NPN	Sw,Sym,4V,0,05A,0,14W,B>500	7e	Son	-
2SC2136	Si-NPN	-		Son	-
2SC2137	Si-NPN	Sw,Pow,500/400V,7A,80W,6MHz,-/<3µS	23a$	Tos	BUW34..36,BUX15,TIP58A,2SC3041..
2SC2138	Si-NPN	=2SC2137:400/300V	23a$	Tos	BUW34..36,BUX15,TIP56A,2SC3041..
2SC2139(A)	Si-NPN	Sw,Pow,500/400V,10A,100W,-/<3µS	23a$	Toshiba	BUW24..26,BUW34..36,2SC3046..
2SC214	Si-NPN	=2SC210:25V,1,5W	2a$	Fui	(BD135,BD226,2SD1200,2SD1378,..)
2SC2140	Si-NPN	=2SC2139:500/350V	23a$	Tos	BUW24..26,BUW34..36,2SC3046..
2SC2141	Si-NPN	AF,Sw-Pow,140/140V,0,5A,50MHz	13j$	Sony	2SC1913(A),2SC2483,2SC2591..2592..
2SC2142	Si-NPN	UHF,15V,0,03A,0,165W,4,5GHz	5g	Son	BFQ22,BFQ63,2SC3037
2SC2143	Si-NPN	UHF,15V,0,03A,0,21W,4,5GHz	25za	Son	BFQ71,BFQ85,BFR14
2SC2144	Si-NPN	UHF,15V,0,02A,0,21W,1,4GHz	25u	Son	2SC2144,2SC2464,2SC2466,2SC2726..
2SC2145	Si-NPN	VHF-Dr/Out,35V,2A,Pq=3,5W(175MHz)	2a$	Mit	BFQ43
2SC2146	Si-NPN	-		Sanyo	-
2SC2147	Si-NPN	Sw,Pow,400/400V,50A,200W,5MHz	68a$	Sak	2SC2159
2SC2148	Si-NPN	UHF-A,LN,30V,0,05A,0,25W,3GHz	51s	Nec	BFQ72,2SC2844
2SC2149	Si-NPN	UHF-A,LN,25V,0,07A,0,29W,5GHz	51s	Nec	BFQ73,2SC3302
2SC215	Si-NPN	=2SC210:80V,1,5W	2a$	Fui	(BD139,BD230,2SD1200,2SD1378,..)
2SC2150	Si-NPN	UHF-A,LN,20V,0,03A,0,25W,6GHz	51s	Nec	BFG91,BFP91,BFQ57..58,BFQ74
2SC2151	Si-NPN	Sw,Pow,600/400V,15A,150W,15MHz	23a$	Fui	BUS13(A),BUW45..46,2SD396,2SD641,..
2SC2152	Si-NPN	UHF-Pow,36V,2A,Pq>7W(500MHz)	56k*	Mat	-
2SC2153	Si-NPN	VHF,LN,30V,0,02A,>450MHz	7a	Mat	BF225,BF314,BF502,BF505,BF507..
2SC2154..2158	Si-NPN	-		Mat	-
2SC2159	Si-NPN	Sw,Pow,400/400V,50A,200W,5MHz	68a$	Sak	2SC2147
2SC216	Si-NPN	HF/Sw,50V,0,3A,0,65W,>100MHz	2a$	Fui	BC140..141,BC300..302,2N3053..
2SC2160	Si-NPN	UHF-Dr/Out,38V,1A,Pq=1,3W(470MHz)	2a$	Fui	BLX65

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2SC2161	Si-NPN	UHF-Dr/Out,38V,1A,Pq=2,5W(470MHz)	55r	Fui	BLW43,BLW80
2SC2162	Si-NPN	UHF-Pow,38V,2A,Pq=5W(470MHz)	55r	Fui	BLW14,BLW44,2N5946
2SC2163	Si-NPN	UHF-Pow,45V,5A,Pq=15W(470MHz)	55r	Fui	BLW15,BLX69,2SC1338..1339,
2SC2164	Si-NPN	UHF-Pow,45V,10A,Pq=30W(470MHz)	57s	Fui	BLU45/12,MRF646,2SC2783
2SC2165(H)	Si-N-Darl+Di	Sw,120V,5A,0,8W,B>1000	5t	Hit	2SC1882
2SC2166	Si-NPN	HF-Pow,75V,4A,Pq>6W(27MHz)	17j$	Mit	2SC1944,2SC1969,2SC2043,2SC2119..
2SC2167	Si-NPN	AF,Sw-Pow,150V,2A,30W,20MHz	17j$	Sak	BD239D,2SC2529,2SC2660,2SD1138..
2SC2168	Si-NPN	=2SC2167:200V	17j$	Sak	BD239F,2SC2660,2SD760,2SD1138..
2SC2169	Si-NPN	VHF-Pow,36V,4A,25W,Pq=9W(175MHz)	61s*	Fui	-
2SC217	Si-NPN	=2SC216:25V	2a$	Fui	BC140..141,BC300..302,2N3053..
2SC2170..2171	Si-NPN	-		Fui	-
2SC2172	Si-NPN	60V,0,2A	35a	Nec	BCW65..66,2SC2882,2SC4209
2SC2173	Si-NPN	UHF-Pow,35V,6A,Pq=28W(470MHz)	55r	Tos	-
2SC2174	Si-NPN	UHF,25V,0,07A,0,35W,4,5GHz	52s	Nec	BFP96,2SC2844,2SC3302
2SC2175	Si-NPN	Sw,Pow,350/350V,10A,100W	23a$	Mitsubishi	BUW24..26,TIP162,2SC2625..26..
2SC2176	Si-NPN	VHF-Pow,50V,3A,Pq=12W(270MHz)	55r	Tos	BLX95,2SC2894
2SC2177	Si-NPN	VHF-Pow,50V,5A,Pq=22W(270MHz)	55r	Tos	2N6105
2SC2178	Si-NPN	VHF-Pow,35V,3,5A,Pq>15W(175MHz)	59r	Tos	MRF222..223
2SC2179	Si-NPN	UHF-Pow,55V,6A,Pq=40W(770MHz)	55r	Fui	-
2SC218	Si-NPN	=2SC216:80V	2a$	Fui	BC140..141,BC300..301,2N1990..
2SC2180	Si-NPN	VHF-Pow,35V,6A,Pq=27W(175MHz)	55r	Tos	BLW20,BLW31,2N6084
2SC2181	Si-NPN	VHF-Pow,35V,10A,Pq>40W(175MHz)	59r	Tos	BLW85
2SC2182	Si-NPN	VHF-Pow,65V,6A,Pq=50W(175MHz)	55r	Tos	BLY94
2SC2183	Si-NPN	UHF-Pow,35V,4,5A,Pq=16W(470MHz)	55r	Tos	BLW15,BLX69,2SC1404,2SC1338
2SC2184	Si-NPN	AM-Pow,60V,3A,Pq=5W(27MHz)	17j$	Fui	2SC1306,2SC1816,2SC1909,2SC2092
2SC2185	Si-NPN	VHF/UHF-Pow,50V,6A,Pq=30W(275MHz)	57s	Nec	2SC2796,2SC2895
2SC2186	Si-NPN	VHF/UHF-Pow,50V,9A,Pq=60W(275MHz)	57s	Nec	MRF327
2SC2187	Si-NPN	-		Nec	-
2SC2188	Si-NPN	VHF,TV-IF,45V,50mA,0,6W,500MHz	9c	Mat	BF225,BF310,BF314,BF502..503..
2SC2189	Si-NPN	Sw,Pow,150V,10A,80W,<1/4µS	23a$	Fujitsu	BD245D,BDX11,2N3442,2SD551,2SC2769
2SC219	Si-NPN	VHF/UHF,20V,25mA,600MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC2190	Si-NPN	Sw,Pow,450V,5A,100W,<1,5/5,3µS	23a$	Fujitsu	BUW71,BUX45,TIP57A..58A,2SC3083..
2SC2191	Si-NPN	Sw,Pow,450V,10A,100W,<2/5,2µS	23a$	Fujitsu	BUW72,BUW75,BUX14,2SC3520..
2SC2192	Si-NPN	VHF-Pow,36V,5A(ss),Pq>15W(175MHz)	56k*	Mat	-
2SC2193	Si-NPN	GenP,150V,0,3A,0,6W,150MHz	2a$	Oki	2SD413,2SD624,(BF380,MPSU10)
2SC2194(A)	Si-NPN	GenP,Pow,60V,1,5A,100MHz	13g$	Toshiba	BD517,BD525,(BD137,BD228,..)
2SC2195	Si-NPN	-		Nec	-
2SC2196	Si-NPN	VHF-Dr/Out,40V,2A,Pq=4,8W(175MHz)	2a*	Fui	(2SC2145)
2SC2197	Si-NPN	VHF-Pow,50V,6A,Pq=30W(160MHz)	55r	Fui	BLW20,BLW31,2N6084
2SC2198	Si-NPN	Hi-beta,Hi-Ueb,100V,6A,40W,B>300	22a$	Sak	(2SC2316,2SC2491)
2SC2199	Si-NPN	Hi-beta,Hi-Ueb,150V,8A,60W,B>300	23a$	Sanken	-
2SC22	Si-NPN	AF/HF/Sw-Pow,75V,0,6A,13W,110MHz	2a$	Nec	(BD139,BD230,BD237,BD830,..)
2SC220	Si-NPN	=2SC210:0,7A	2a$	Fui	→2SC210
2SC2200	Si-NPN	Sw,Pow,500/400V,7A,40W	22a$	Tos	BUT56(A),2SC2335,2SC2427,2SC3039,..
2SC2201	Si-NPN	-		Tos	-
2SC2202..2203	Si-NPN	-		Fui	-
2SC2204	Si-NPN	Sw,Pow,800/400V,30A,250W,<1,5/5µS	68a$	Tos	2SC2977,2SD295
2SC2205	Si-NPN	Dual,45V,0,03A,0,4W,2,2GHz	84bg1	Nec	-
2SC2206	Si-NPN	GenP,LN,30V,0,03A,0,4W,300MHz	9c	Mat	BC238,BC548,BF240..41,BF254..55..
2SC2207	Si-NPN	AM-Pow,80V,8A,Pq=14W(27MHz)	17j$	Hit	2SC1307
2SC2208(H)	Si-N-Darl+Di	Sw,120V,5A,0,8W,B>1000	2a$	Hit	-
2SC2209	Si-NPN	AF,Sw-Pow,50V,1,5A,10W,150MHz	14h$	Mat	BD137,BD228,BD375,2SD1177..78..
2SC221	Si-NPN	=2SC211:0,7A	2a$	Ful	→2SC211
2SC2210	Si-NPN	AM-Pre/Mix/Osc/IF,90MHz	7c	Sanyo	BF240..241,BF254..255,BF594..595,..
2SC2211	Si-NPN	-		Son	-
2SC2212	Si-NPN	VHF/UHF,LN,1400MHz	7e	Son	BF377..378,BF689K,BF763,2N2857..
2SC2213	Si-NPN	UHF,30V,0,05A,0,25W,2,5GHz	7c	Son	2SC2570(A),2SC3037,2SC3337
2SC2214	Si-NPN	AF,Sw,100V,4A,1W,140MHz,75/610nS	2a$	Son	BFT33..34,2N4239,2N5338..39,2SC696(A)
2SC2215	Si-NPN	TV-IF-AGC,40V,0,05A,>400MHz	7f	Tos	BF198,BF225,BF310,BF367,BF596..
2SC2216	Si-NPN	TV-IF-Out,50V,0,05A,>300MHz	7f	Tos	BF199,BF224,BF311,BF373,BF959..
2SC2217	Si-NPN	UHF-A,20V,0,08A,0,58W,8GHz	51s	Nec	2SC2876,2SC3062,2SC3358,2SC3603
2SC2218	Si-NPN	UHF-A,20V,0,08A,0,35W,8GHz	52s	Nec	2SC2876,2SC3062,2SC3358,2SC3603
2SC2219	Si-NPN	UHF-A,20V,0,08A,0,7W,8GHz	-	Nec	-
2SC222	Si-NPN	=2SC212:0,7A	2a$	Fui	→2SC212

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2SC2220	Si-NPN	Sw,Pow,500/300V,30A,250W,<1,5/5μS	68a$	Tos	2SC1300,2SC1471,2SC1874,2SC2444
2SC2221	Si-NPN	VHF-Dr/Out,25V,0,75A,Pq>1,6W(175MHz)	2a	Nec	(BFQ42,BFR98,BLW16,BLY61)
2SC2222	Si-NPN	VHF-Pow,25V,1,5A,Pq>5W(175MHz)	55s	Nec	(BLW19,BLW37,MRF212,2N5590)
2SC2223	Si-NPN	FM/VHF,30V,0,02A,600MHz	35a	Nec	BF599,BF799,BFS20,2SC3015
2SC2223-F12	Si-NPN	-	3S	Nec	→2SC2223
2SC2223-F13	Si-NPN	-	3S	Nec	→2SC2223
2SC2223-F14	Si-NPN	-	3S	Nec	→2SC2223
2SC2223-F6	Si-NPN	-	3S	Nec	→2SC2223
2SC2224	Si-NPN	AF/Vid-Pow,200V,0,2A,10W,100MHz	13g$	NEC	BF381..382,BF615,BF617,MPSU10
2SC2224A	Si-NPN	=2SC2224:250V	13g$	-	BF381..382,BF615,BF617,MPSU10
2SC2225..2226	Si-NPN	-		Nec	-
2SC2227	Si-NPN	UHF,35V,0,2A,2,4GHz	5g	Nec	2SC1253,2SC1366,2SC1952
2SC2228	Si-NPN	160V,0.05A,0.75W,B>50	-		-
2SC2228(Y)	Si-NPN	Vid,160/160V,0,05A,0,75W,>50MHz	7c(9mm)	Sanyo	BF297..299,BF422A,2SC3467..69..
2SC2228A	Si-NPN	=2SC2228:200/200V	7c(9mm)	-	BF298..299,BF422A,2SC3467..69..
2SC2229	Si-NPN	AF-Driver,Vid,200V,0,05A,0,8W,120MHz	7c(9mm)	Tos	BF298..299,BF422A,2SC3467..69..
2SC223	Si-NPN	=2SC213:1A	2a$	Fui	→2SC213
2SC2230	Si-NPN	200V,0.1A,0.8W,50MHz	-		-
2SC2230(A)	Si-NPN	AF-Driver,Vid,200V,0,1A,0,8W,>50MHz	7c(9mm)	Tos	BF298..299,BF422A,2SC3467..69..
2SC2231(A)	Si-NPN	TV-AF-Pow,200V,0,2A,12W,>50MHz	13j$	Toshiba	(BF615,BF617,BF757..759,MPSU10)
2SC2232	Si-NPN	-		Nec	-
2SC2233	Si-NPN	TV-HD,200/60V,4A,40W,8MHz	17j$	Tos	BU406..408,2SD823,2SD1136,2SD1159,..
2SC2234	Si-NPN	VHF-Pow,35V,10A,Pq>40W(175MHz)	55r	Tos	-
2SC2235	Si-NPN	GenP,120/120V,0,8A,0,9W,120MHz	7c(9mm)	Tos	2SC2383,2SC3228,2SD667,2SD1812..
2SC2236	Si-NPN	AF-Dr/Out,30V,1,5A,0,9W,120MHz	7c(9mm)	Tos	2SC3328,2SD1146,2SD1207,2SD2069..
2SC2237	Si-NPN	HF-Pow,35V,2A,Pq>7,5W(175MHz)	58s*	Mit	-
2SC2238	Si-NPN	AF,Sw-Pow,160/160V,1,5A,25W,100MHz	17j$	Tos	2SC2592,2SC2660,2SC2529,2SD1138..
2SC2238A	Si-NPN	=2SC2238:180/180V	17j$	-	2SC2592,2SC2660,2SC2344,2SD1138..
2SC2238B	Si-NPN	=2SC2238:200/200V	17j$	-	2SC2660,2SD760,2SD1138
2SC2239	Si-NPN	=2SC2238:	22a$	Tos	2SC783,2SC2529,2SC2592,2SD1138..
2SC224	Si-NPN	=2SC214:1A	2a$	Fui	→2SC214
2SC2240	Si-NPN	AF,LN,120/120V,0,1A,0,3W,100MHz	7c	Tos	2SC2362,2SC2389,2SC2459,2SC2631..32..
2SC2241	Si-NPN	AF/Vid-Pow,300/300V,0,15A,20W,>50MHz	17j$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC2242	Si-NPN	AF/Vid-Pow,300/300V,0,15A,25W,50MHz	17j$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC2243	Si-NPN	Sw,Pow,450/400V,5A,100W,<1/3μS	23a$	Fujitsu	BUW71,BUX44..45,TIP57A..58A..
2SC2244	Si-NPN	=2SC2243:8A	23a$	Fjd	BUW72,BUX15,BUX44,TIP57A..58A..
2SC2245	Si-NPN	=2SC2243:10A	23a$	Fjd	BUW24..26,BUW34..36,BUW72,2SC3520+
2SC2246	Si-NPN	=2SC2243:15A	23a$	Fjd	BUV25,BUW44,BUX25,2SC4140..
2SC2247	Si-NPN	=2SC2243:40W	22a$	Fjd	MJE53T,2SC1865,2SC2200,2SC3056..
2SC2248	Si-NPN	=2SC2243:8A,40W	22a$	Fjd	BUY65,MJE13006,2SC3057,2SC4107..
2SC2249	Si-NPN	Sw,Pow,250/200V,30A,200W,<2,5μS	68a$	Fjd	2SC1301,2SC1873,2SC2445,2SD643..
2SC225	Si-NPN	=2SC215:1A	2a$	Fui	→2SC215
2SC2250	Si-NPN	=2SC2249:450/400V	68a$	Fjd	2SC1300,2SC1470,2SC1874,2SC2220..
2SC2251	Si-NPN	UHF-Dr/Out,45V,0,5A,Pq=1,8W(900MHz)	55r	Fui	BLX97
2SC2252	Si-NPN	UHF-Dr/Out,45V,1A,Pq=4,5W(900MHz)	55r	Fui	-
2SC2253	Si-NPN	UHF-Pow,45V,2A,Pq=9W(900MHz)	55r	Fui	-
2SC2254	Si-NPN	UHF-Pow,45V,4A,Pq=12W(900MHz)	55r	Fui	-
2SC2255	Si-NPN	UHF-Pow,45V,6A,Pq=22W(900MHz)	?57s	Fui	2SC2044
2SC2256	Si-NPN	Sw,Pow,200/150V,15A,150W,10MHz	23a$	Sanken	BDW16,BUW50,BUX41,2SD552,2SD583..
2SC2257	Si-NPN	Vid-Pow,180/180V,0,05A,80MHz	14h$	Mat	BF415,BF458,BF469,2SC3502..
2SC2257A	Si-NPN	=2SC2257:220/220V	14h$	-	BF415,BF458,BF469,2SC3503..
2SC2258	Si-NPN	Vid-Pow,250/250V,0,1A,4W,100MHz	14h$	Mat	BF415,BF458,2SC3417,2SC3503..
2SC2258A	Si-NPN	=2SC2258:300/300V	14h$	-	BF417,BF459,BF850,2SC3417..18
2SC2258B	Si-NPN	=2SC2258:400/400V	14h$	-	BF850,2SC3418
2SC2259	Si-NPN	Dual,LN,100V,0,05A,0,4W,150MHz	5-SIP/ba	Mit	-
2SC226	Si-NPN	=2SC216:0,7A	2a$	Fui	→2SC216
2SC2260	Si-NPN	AF,Sw-Pow,160/160V,8A,80W,15MHz	23a$	Sak	BD245D,BDX11,2N3442,2SD733,2SD551,.
2SC2261	Si-NPN	=2SC2260:180/120V	23a$	Sak	MJ15015,BD245E,BDW14,2SC2607..
2SC2262	Si-NPN	=2SC2260:200/140V	23a$	Sak	MJ15015,BD245F,BDW16,2SC2607..
2SC2263	Si-NPN	GenP,LN,60V,0,05A,0,25W,70MHz	7c	Mat	2SC2390,2SC1775(A),2SC2631..32..
2SC2264	Si-NPN	GenP,90V,1A,0,75W,200MHz	7c(9mm)	Mat	2SC3228,2SD667,2SD1292,2SD1812..
2SC2265(H)	Si-NPN	VHF,LN,35V,0,02A,550MHz	5g	Hit	BF314,BFS02..503,2SC1393,2SC1856,..
2SC2266	Si-NPN	Sw,Pow,500/400V,10A,100W,<1,5/3,5μS	23a$	Hitachi	BUW25..26,BUW34..36,2SC3043,2SC3520
2SC2267	Si-NPN	400/360V,0.1A,0.4W	-		-

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2SC2267(H)	Si-NPN	Sw,Vid,400/360V,0,1A,0,4W,70MHz	2a	Hit	MPSA44..45,2SC3118,2SC3469,2SD1350..
2SC2268..2269	Si-NPN	-		Tos	-
2SC227	Si-NPN	=2SC217:0,7A	2a$	Ful	→2SC217
2SC2270	Si-NPN	Sw,Pow,Lo-sat,50V,5A,10W,100MHz	14h$	Tos	2SC3420,2SD826,2SD2147
2SC2271	Si-NPN	Vid,300/300V,0,1A,0,9W,>50MHz	7c(9mm)	Sanyo	2SC3249,2SC3468..3469,2SC4166
2SC2272	Si-NPN	UHF,LN,20V,0,035A,0,44W,10GHz	52s	Nec	2SC3584,2SC3586..3587
2SC2273	Si-NPN	UHF,LN,25V,0,065A,0,44W,8,5GHz	52s	Nec	BFG195,2SC3062
2SC2274	Si-NPN	GenP,60V,0,5A,0,6W,120MHz	7c	Sanyo	BC637,BC639,2SC4414,2SD1226..
2SC2274K	Si-NPN	=2SC2274:100V	7c	-	BC639,2SC3665,2SC4414,2SD667..
2SC2275	Si-NPN	AF/HF-Pow,120/120V,1,5A,25W,200MHz	17j$	Nec	2SC2238,2SC2344,2SC2528..29
2SC2275A	Si-NPN	=2SC2275:150/150V	17j$	-	2SC2238,2SC2344,2SC2529,2SC2660
2SC2276	Si-NPN	AF/HF/Sw-Pow,130/130V,7A,80W,100MHz	19j$	Nec	2SD588,2SD848A
2SC2277	Si-NPN	GenP,50V,0,5A,0,625W,120MHz	7e	Hit	BC337,BC637,2SD1226,2SD2322S..
2SC2278	Si-NPN	Vid-Pow,300/300V,0,1A,80MHz	17g$	Hit	BF382,BF461..462,MPSU10,2SC1758,..
2SC2279	Si-NPN	Vid-Pow,300/300V,0,1A,10W,35MHz	13g$	Toshiba	BF382,BF461..462,MPSU10,2SC1758..
2SC228	Si-NPN	=2SC218:0,7A	2a$	Fui	→2SC218
2SC2280	Si-NPN	HF-Pow,-/18V,0,75A,10W	55s	Nec	-
2SC2281	Si-NPN	VHF-Pow,38V,1,5A,Pq>7,1W(175MHz)	55s	Nec	BLW19,BLW37,MRF212,2N5590
2SC2282	Si-NPN	VHF-Pow,38V,3A,Pq>15W(175MHz)	55s	Nec	BLY89,MRF209,2N5591,2N6082
2SC2283	Si-NPN	UHF-Dr/Out,38V,0,75A,Pq>2,8W(500MHz)	58r*	Nec	2SC3020
2SC2284(A)	Si-NPN	UHF-Pow,38V,1,5(A=2)A,Pq>7,1W(500MHz)	58r*	Nec	2SC3021
2SC2285(A)	Si-NPN	UHF-Pow,38V,3(A=4)A,Pq>14,1W(500MHz)	58r*	Nec	-
2SC2286	Si-NPN	VHF-Dr/Out,38V,0,75A,Pq>2,5W(175MHz)	58r*	Nec	-
2SC2287	Si-NPN	38V,1.5A,7.1W,175MHz	-		-
2SC2287(K)	Si-NPN	VHF-Pow,38V,1,5A,Pq>7,1W(175MHz)	58r*	Nec	-
2SC2287M	Si-NPN	=2SC2287:	?58r	-	-
2SC2288(K)	Si-NPN	VHF-Pow,38V,3A,Pq>15W(175MHz)	58r*	Nec	2SC2094
2SC2288M	Si-NPN	=2SC2288:	?58r	-	-
2SC2289(K)	Si-NPN	VHF-Pow,25V,1,5A,Pq>5W(175MHz)	58r*	Nec	-
2SC2289M	Si-NPN	=2SC2289:	?58r	-	-
2SC229	Si-NPN	AF,Sw-Pow,80V,1A	2a$	Fui	(BD139,BD230,2SD1200,2SD1378,..)
2SC2290	Si-NPN	AM/SSB-Pow,45V,20A,Pep=60W(28MHz)	59r	Tos	MRF421,MRF454
2SC2291	Si-NPN	Dual,100V,0,1A,0,4W,100MHz	5-SIP/bd	Mit	-
2SC2292	Si-NPN	Sw,Pow,500/400V,8A,80W,20MHz	23a$	Shi	BUW25..26,BUW34..36,2SC3046..
2SC2293	Si-NPN	=2SC2292:10A,100W	23a$	Shi	BUW25..26,BUW34..36,2SC3046..
2SC2294	Si-NPN	FM,30V,0,03A,300MHz	7c	Mat	BF225,BF310,BF314,BF502,BF505..
2SC2295	Si-NPN	AM/FM,LN,30V,0,03A,250MHz	35a	Matsushita	BC849..850,BF554,BF840..841
2SC2295-A	Si-NPN	-	35	Mat	→2SC2295
2SC2295-B	Si-NPN	-	35	Mat	→2SC2295
2SC2295-C	Si-NPN	-	35	Mat	→2SC2295
2SC2296	Si-NPN	HF,30V,0,03A,0,2W,230MHz	7c	Mit	BC238,BC548,BF240..41,BF254..55..
2SC2297	Si-NPN	AM-Pow,55V,8A,Pq>16W(27MHz)	17j$	Hit	2SC1817
2SC2298(A,B)	Si-NPN-Darl	AF,Sw-Pow,30V,1A,8W,B>4000	14h$	Hit	BD477A,B,BD875,2SC4340..41
2SC2299	Si-NPN	GenP,20V,1A,0,5W,150MHz	7c	Fujitsu	BC337..338,BC635,BC637,2SC3377..
2SC23	Si-NPN	=2SC22:0,5A	2a$	Nec	(BD139,BD230,BD237,BD830,..)
2SC230	Si-NPN	HF/Sw,80V,0,2A,0,35W,350MHz	2a$	Fui	BSW63..64,2N2221A..2222A
2SC2300	Si-NPN	=2SC2299:50V	7c	Fui	BC337,BC635,BC637,2SD1226..
2SC2301	Si-NPN	UHF-Pow,45V,2,8A,Pq=16W(890MHz)	-	Nec	-
2SC2302	Si-NPN	Sw,Pow,500/400V,7A,40W,35MHz	22a$	Sak	2SC2427,2SC2739,2SC3039,2SC4106..
2SC2303	Si-NPN	Sw,Pow,500/400V,10A,80W,35MHz	23a$	Sanken	BUW25..26,BUW34..36,2SC3046..
2SC2304	Si-NPN	Sw,Pow,500/400V,12A,100W,35MHz	23a$	Sanken	BUW44,BUW75..77,BUX25,2SC3043..
2SC2305	Si-NPN	Sw,Pow,400/400V,7A,80W	18j$	Sak	BU426(A),BU926,TIP57A..58A,2SC3040
2SC2306	Si-NPN	Sw,Pow,450/400V,15A,150W,7MHz	23a$	Sanken	BUV25,BUW44..45,BUX25,2SD641..
2SC2307	Si-NPN	Sw,Pow,500/400V,12A,100W,18MHz	18j$	Sak	BUV48(A..C),BUW13(A),2SC3520..
2SC2308	Si-NPN	GenP,55V,0,1A,0,2W,230MHz,B>100	7c	Hit	BC167,BC182,BC237,BC547,2SD767..
2SC2309	Si-NPN	GenP,55V,0,1A,0,2W,230MHz,B>250	7c	Hit	2SC3622..23,(BC182,BC237,BC547,..)
2SC231	Si-NPN	AF,Sw,50V,0,7A,0,65W	2a$	Fui	BC140..141,BC300..302,2N3053..
2SC2310	Si-NPN	=2SC2308:ra	7c	Hit	BC414,BC550,2SC2240,2SC2459..
2SC2311	Si-NPN	Sw,Pow,50V,1A,45/90nS	14h$	Fui	BD137,BD228,BD375,2SD1177..78..
2SC2312	Si-NPN	HF-Pow,60V,6A,Pq=18,5W(27MHz)	17j$	Mit	2SC1307,2SC1944,2SC1969,2SC1817..
2SC2313	Si-NPN	AM/FM-Pow,40V,10A,Pq=38W(65MHz)	55r*	Mit	-
2SC2314	Si-NPN	AM-Pow,75V,1A,Pq=1,8W(27MHz)	14h$	Sanyo	-
2SC2315	Si-NPN	Hi-beta,80V,6A,40W,B=800	17j$	Sak	2SC2316,2SC2491,2SD1158
2SC2316	Si-NPN	=2SC2315:100V	17j$	Sak	2SC2316,2SC2491

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2SC2317	Si-NPN	Hi-beta, 200V, 1A, 30W, B=1000	17j$	Sak	2SD1272
2SC2318	Si-NPN	VHF/UHF-A/Out, 40V, 0,35A, 2700MHz	5g	Tos	2SC1199, 2SC1252, 2SC1365..66, 2SC2852
2SC2319	Si-NPN	VHF/UHF-A/Out, 40V, 0,35A, 2900MHz	55r	Tos	2N5944
2SC232	Si-NPN	=2SC231: 25V	2a$	Fui	BC140..141, BC300..302, 2N3053..
2SC2320	Si-NPN	GenP, 50V, 0,2A, 0,3W, 200MHz	7c	Mit	BC167, BC182, BC237, BC547, 2SD767..
2SC2320L	Si-NPN	=2SC2320: ra	7c	-	BC414, BC550, 2SC2240, 2SC2459..
2SC2321	Si-NPN	AF, Sw-Pow, 130/130V, 8A, 80W, 60MHz	23a$	Fui	2SC1584, 2SD1047, 2SD425, 2SD551..
2SC2322	Si-NPN	AF, Sw-Pow, 120/120V, 12A, 120W, 60MHz	23a$	Fui	2SC1584, 2SD1047, 2SD425, 2SD551..
2SC2323	Si-NPN	=2SC2322: 150/150V	23a$	Fui	2SC1584, 2SD1047, 2SD733, 2SD551..
2SC2324(K)	Si-NPN-Darl	AF, Sw-Pow, 60V, 1A, 8W, B>2000	14h$	Hit	BD677, BD875, BDX42..44, 2SD985..86..
2SC2325	Si-NPN	HF-Pow, 45V, 0,6A, Pq>1,3W(4,2GHz)	62a&	Nec	-
2SC2326	Si-NPN	HF-Pow, 45V, 1,2A, Pq>2,5W(4,2GHz)	62a&	Nec	-
2SC2327	Si-NPN	UHF, LN, 20V, 0,03A, 4,5GHz	24b	Tos	BFQ69, BFR91
2SC2328	Si-NPN	Min, UHF, LN, 20V, 0,03A, 2,2GHz	24b	Tos	BFT24, BFR34, BFW93
2SC2329	Si-NPN	VHF-A/Dr/Out, 38V, 0,75A, Pq>2W(175MHz)	2a	Nec	BF522, BFW46, BLY33, MRF237, 2N3924
2SC233	Si-NPN	=2SC231: 80V	2a$	Fui	BC140..141, BC300..301, 2N1990..
2SC2330	Si-NPN	VHF-Pow, 38V, 6A, Pq>31,6W(175MHz)	58r*	Nec	-
2SC2331	Si-NPN	Sw, Pow, 150/100V, 2A, 15W, <0,5/2µS	17j$	Nec	BD239F, 2SC2660, 2SD760, 2SD1138..
2SC2332	Si-NPN	-		Nec	-
2SC2333	Si-NPN	Sw, Pow, 500/400V, 2A, 15W, <1/3,5µS	17j$	Nec	BUV36(A), BUX84..85, 2SC2534, 2SC2738
2SC2334	Si-NPN	Sw, Pow, 150/100V, 7A, 40W, <0,5/2µS	17j$	Nec	BD243F, BU409, BUW64C, TIP150..152
2SC2335	Si-NPN	Sw, Pow, 500/400V, 7A, 40W, <1/3,5µS	17j$	Nec	BUT56(A), 2SC2427, 2SC2739, 2SC3039
2SC2336	Si-NPN	AF/HF-Pow, 180/180V, 1,5A, 25W, 95MHz	17j$	Nec	2SC2238A,B, 2SC2660, 2SD608A, 2SD760
2SC2336A	Si-NPN	=2SC2336: 200V	17j$	-	2SC2238B, 2SC2660, 2SD610, 2SD760
2SC2336B	Si-NPN	=2SC2336: 250V	17j$	-	2SC2023, 2SD610
2SC2337(A)	Si-NPN	AF, Sw-Pow, 150V, 10A, 100W, 70MHz	23a$	Nec	BDX11, 2SD1047, 2SD551, 2SD733..
2SC2338	Si-NPN	UHF-Osc, 25V, 0,04A, Pq=0,14W(7,5GHz)	52s	Nec	2SC3584, 2SC3586..3587
2SC2339	Si-NPN	UHF-Osc, 25V, 0,15A, Pq=0,2W(6GHz)	55s	Nec	-
2SC234	Si-NPN	AF, Sw-Pow, 100V, 1,5A, 18W, 140MHz	2a$	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2340	Si-NPN	UHF-Dr/Out, 30V, 0,3A, 6W, 6,5GHz	62d*	Nec	-
2SC2341	Si-NPN	UHF-Osc, 25V, 0,04A, Pq=0,14W(7,5GHz)	-	Nec	-
2SC2342	Si-NPN	UHF-Osc, 25V, 0,15A, Pq=0,2W(6GHz)	-	Nec	-
2SC2344	Si-NPN	AF, Sw-Pow, 180/160V, 1,5A, 25W, 100MHz	17j$	Sanyo	2SC2238A,B, 2SC2660, 2SD608A
2SC2345	Si-NPN	UHF, LN, AGC, 25V, 0,02A, 980MHz	?42	Tos	(2SC2464..66, 2SC2360, 2SC2726,..)
2SC2346	Si-NPN	-		Tos	-
2SC2347	Si-NPN	VHF-Mix, UHF-Osc, 30V, 0,05A, >650MHz	7c	Tos	BF377..378, BF689K, BF763, 2N2857..
2SC2348	Si-NPN	VHF-Pre, AGC, 30V, 0,02A, >400MHz	7f	Tos	BF314, BF496, BF502, BF505, BF507..
2SC2349	Si-NPN	VHF-Osc, 30V, 0,05A, >600MHz	7c	Tos	BF199, BF224, BF311, BF503, BF505..
2SC235	Si-NPN	=2SC234: 120MHz	2a$	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2350	Si-NPN	UHF, LN, 30V, 0,05A, 2,8GHz	35a	Nec	BFR53, 2SC3014, 2SC3773
2SC2351	Si-NPN	UHF, LN, 25V, 0,07A, 4,5GHz	35a	Nec	BFR106, 2SC3161, 2SC3774
2SC2351-P	Si-NPN	npn RF fT 4.5 GHz hfe 40-120	-	Nec	-
2SC2351-Q	Si-NPN	npn RF fT 4.5 GHz hfe 100-200	-	Nec	-
2SC2351-R2	Si-NPN	-	35	Nec	→2SC2351
2SC2351-R3	Si-NPN	-	35	Nec	→2SC2351
2SC2352	Si-NPN	VHF, 30V, 0,03A, 850MHz	7f	Nec	BF225, BF310, BF314, BF505, BF507..
2SC2353	Si-NPN	UHF, 30V, 0,05A, 2,3GHz	25u	Nec	2SC2466, 2SC2728
2SC2354	Si-NPN	AF, Sw-Pow, 300/250V, 1A, 30W, 20MHz	22a$	Sak	BUX67A..C, TIP47..50, 2SC782, 2SD860..
2SC2355	Si-NPN	-		Tos	-
2SC2356	Si-NPN	Sw, Pow, 500/400V, 10A, 100W, 20MHz	23a$	Fujitsu	BUW25..26, BUW34..36, 2SC3046..
2SC2357	Si-NPN	Sw, Pow, 1000/700V, 10A, 150W, -/3,3µS	23a$	Fujitsu	BUS12A, BUX81, BUY69A..70A, MJ8504..
2SC2358	Si-NPN	=2SC2357: 1000/800V	23a$	Fui	BUS12A, BUX81, BUY69A..70A, MJ8504..
2SC2359	Si-NPN	Sw, Pow, 450/400V, 4A, 40W, 20MHz, -/1,9µS	22a$	Fui	BUT93, BUX64, MJE53T, TIP75B,C..
2SC236	Si-NPN	=2SC234: 90V, 100MHz	2a$	Fui	(BD139, BD230, BD379, 2SD1177..1178
2SC2360	Si-NPN	UHF, 30V, 20mA, 0,2W, 1100MHz	25u	Mat	2SC2464, 2SC2466, 2SC2353, 2SC2726
2SC2361	Si-NPN	AF, Sw-Pow, 70V, 4A, 25W, 70MHz	17j$	Mat	BDV10..12, MJE15028, 2SC3253, 2SD772..
2SC2361A	Si-NPN	=2SC2361: 100V	17j$	-	BDV10..12, MJE15028, MJE15030, 2SD772
2SC2362	Si-NPN	GenP, LN, 120V, 0,05A, 0,4W, 130MHz	7c	Sanyo	2SC1845, 2SC2088, 2SC2240, 2SC2389..
2SC2362K	Si-NPN	=2SC2362: 150/120V	7c	-	2SC2631..32, 2SC3800
2SC2363	Si-NPN	AF-Driver, 120V, 0,05A, 0,5W, 130MHz	7c	Sanyo	2SC1890A, 2SC2375, 2SC3245, 2SD756A..
2SC2364	Si-NPN-Darl	Sw, Pow, 200/150V, 5A, 80W, B=1000	18j$	Sak	2SD921, 2SD933, 2SD1090, 2SD1122..
2SC2365	Si-NPN	Sw, Pow, 600/500V, 6A, 50W, 10MHz	23a$	Sak	BU326, BU426, BU526, BUX47(A)..
2SC2366	Si-NPN	Sw, Pow, 500/400V, 40A, 300W, 15MHz	68a$	Fui	2SC1435, 2SD642
2SC2367	Si-NPN	UHF-A, LN, 20V, 0,08A, 0,58W, 8GHz	51s	Nec	BFQ82, BFQ196, 2SC3603

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2SC2368	Si-NPN	UHF,30V,0,05A,0,25W,2,8GHz	2Sza	Nec	2SC2368,2SC2470,2SC3368
2SC2369	Si-NPN	UHF,25V,0,07A,0,25W,4,5GHz	2Sza	Nec	BFP96,BFQ73,2SC2844,2SC3302
2SC237	Si-NPN	VHF-A/Dr,25V,0,3A,0,35W,450MHz	2a$	Fui	2SC2851,(BFX55)
2SC2370	Si-NPN	UHF-Dr/Out,35V,0,8A,Pq=4W(470MHz)	51r	Tos	-
2SC2371	Si-NPN	Vid-Pow,TV-HD/VD-Dr,300V,0,1A,10W	14h$	Nec	BF417,BF459,2SC3417,2SC3503..
2SC2373	Si-NPN	TV-HD,200/100V,7,5A,40W,10MHz	17j$	Nec	BU406..408,2SC3189,2SC3589,2SD1069..
2SC2374	Si-NPN	-		Nec	-
2SC2375	Si-NPN	AF-Driver,150V,0,05A,0,9W,130MHz	7c(9mm)	Sanyo	2SC2632,2SC3245(A),2SC3248,2SC3800,..
2SC2376	Si-NPN	TV-AF-Pow,TV-HD-Dr,300V,0,15A,20W	14h$	Tos	MJE340,MJE3439..3440,2SC2899
2SC2377	Si-NPN	AM/FM/VHF,30V,15mA,0,4W,650MHz	9c	Mat	BF225,BF310,BF314,BF502,BF505..
2SC2378	Si-NPN	AF,70V,0,1A,0,25W,250MHz	7c	Nec	BC174,BC546,2SC2240,2SC2675..
2SC2379	Si-NPN	UHF-Pow,35V,1,4A,Pq>6W(470MHz)	59r	Tos	-
2SC238	Si-NPN	AF/HF,40V,0,1A,0,65W,350MHz	2a$	Fui	BFW16..17,BFX55,2N3724,2SC1385..
2SC2380	Si-NPN	UHF-Pow,35V,2,8A,Pq>12W(470MHz)	59r	Tos	-
2SC2381	Si-NPN	UHF-Pow,35V,6A,Pq>25W(470MHz)	59r	Tos	-
2SC2382	Si-NPN	VHF-Pow,40V,12A,Pq>50W(175MHz)	59r	Tos	MRF243
2SC2383	Si-NPN	CTV-AF/VD,160/160V,1A,0,9W,>20MHz	7c(9mm)	Tos	2SC3228,2SD1812
2SC2384	Si-NPN	=2SC2383:10W	13g$	Tos	(2SC1913,2SC2592,2SD387(A),2SD1138)
2SC2385	Si-NPN	GenP,LN,70V,0,1A,0,2W,130MHz	7b	Mit	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2SC2386	Si-NPN	GenP,70V,0,3A,0,5W,125MHz	7b	Mit	BC546,BC639,2SC4414,2SD1226..
2SC2387	Si-NPN	Sw,Pow,500V,8A,100W,1/2,1µS	23a$	Hit	BUW25..26,BUW34..36,2SC3046..
2SC2388	Si-NPN	Sw,Pow,450/400V,4A,75W,20MHz,-/1,9µS	23a$	Fujitsu	BU326,BU426,BUX45,2SC3083..
2SC2388A	Si-NPN	=2SC2388:500/400V,7A	23a$	-	BU326,BU426,BUX15,2SC2536..
2SC2389	Si-NPN	120V,50mA,0.3W,140MHz	-		-
2SC2389(S)	Si-NPN	GenP,LN,120V,0,05A,0,3W,140MHz	7c,41c	Rhm	2SC1845,2SC2088,2SC2240,2SC2459..
2SC239	Si-NPN	Sw,50V,0,3A,0,35W,450MHz,<-/150nS	2a$	Fui	BSS10,BSX19..20,BSX39,2N3261..
2SC2390	Si-NPN	=2SC2389:80V	7c	Rhm	2SC1845,2SC2089,2SC2240,2SC2459..
2SC2391	Si-NPN	UHF-Dr/Out,35V,0,8A,Pq>3W(470MHz)	59r	Tos	-
2SC2392	Si-NPN	UHF-Pow,35V,2,8A,Pq>15W(470MHz)	59r	Tos	-
2SC2393	Si-NPN	AM-Pow,80V,4A,Pq>6W(28MHz)	17j$	Tos	2SC1816,2SC2119
2SC2394	Si-NPN	AM-Pow,45V,6A,Pq=16W(50MHz)	17j$	Tos	2SC2050
2SC2395	Si-NPN	AM-Pow,40V,5A,Pep=10W(28MHz)	59r	Tos	2SC2693
2SC2396	Si-NPN	GenP,60V,0,1A,0,4W,90MHz	7c	Hit	BC174,BC182,BC190,BC546,2SD767..
2SC2397	Si-NPN	AM-Pow,60V,8A,Pq>18W(27MHz)	17j$	Hit	2SC1817
2SC2398	Si-NPN	AF,Sw-Pow,100V,10A,95W,80MHz	23a$	Son	2SC2681,2SC2706,2SC2837
2SC2399	Si-NPN	VHF/UHF,30V,0,02A,940MHz	7e	Hit	BF377..378,BF689K,BF763,2N2857..
2SC24	Si-NPN	=2SC22:100V,0,5A	2a$	Nec	(BD139,BD230,BD237,BD830,..)
2SC240	Si-NPN	Sw,Pow,100V,5A,75W	23a$	NEC	BD245C,BDV95,BDX95,2N5758..60..
2SC2400	Si-NPN	Fast-Sw,40V,0,1A,0,31W,<10/15nS	7e	Hit	BSV91..92,BSX92..93,2N2368..69(A),..
2SC2401	Si-NPN-Darl	GenP,40V,0,3A,0,31W,B=10000	7e	Hit	BC517,BC617,BC875,MPSA25..29..
2SC2402	Si-NPN	Sw,Pow,300/200V,15A,150W,-/2,3µS	23a$	Fujitsu	BUX13,BUY50,MJ15022,MJ15024..
2SC2403	Si-NPN	Sw,Pow,300/200V,40A,300W,-/3µS	68a$	Fui	2SC2366,2SC2973,2SD702
2SC2404	Si-NPN	-	3S	Mat	→2SC2404
2SC2404-B	Si-NPN	-	3S	Mat	→2SC2404
2SC2404-C	Si-NPN	-	3S	Mat	→2SC2404
2SC2404-D	Si-NPN	-	3S	Mat	→2SC2404
2SC2405	Si-NPN	LN,35V,0,05A,200MHz	3Sa	Mat	BC849..850,BCF32..33,BCF81,2SC3323
2SC2405-R	Si-NPN	-	3S	Mat	→2SC2405
2SC2405-S	Si-NPN	-	3S	Mat	→2SC2405
2SC2405-T	Si-NPN	-	3S	Mat	→2SC2405
2SC2406	Si-NPN	-	3S	Mat	→2SC2406
2SC2406-R	Si-NPN	-	3S	Mat	→2SC2406
2SC2406-S	Si-NPN	-	3S	Mat	→2SC2406
2SC2406-T	Si-NPN	-	3S	Mat	→2SC2406
2SC2407	Si-NPN	UHF-Osc,35V,0,15A,Pq=0,16W(500MHz)	7f	Nec	2SC1954
2SC2408	Si-NPN	HF-Ant,35V,0,15A,0,6W,3,5GHz	7f	Nec	2SC3337
2SC2409	Si-NPN	AF,LN,50V,0,1A,0,3W,180MHz	7c	Rhm	BC184,BC414,BC550,2SC2240..
2SC241	Si-NPN	=2SC240:60V	23a$	Nec	BD245A,BDV91,BDX91,2N4914..15..
2SC2410(S)	Si-NPN	HF,40V,0,1A,0,25W,230MHz	7c,41c	Rhm	BF240..241,BF254..255,BF594..595,..
2SC2411	Si-NPN	40V,0,5A,250MHz	?35d	Rhm	-
2SC2411-CP	Si-NPN	-	?3S	Rhm	→2SC2411
2SC2411-CQ	Si-NPN	-	?3S	Rhm	→2SC2411
2SC2411-CR	Si-NPN	-	?3S	Rhm	→2SC2411
2SC2411K	Si-NPN	=2SC2411:	3Sa	-	BC817,BCW65..66,BCX19,2SC3325..

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2SC2411K-P	Si-NPN	-	3S	Rhm	→2SC2411K
2SC2411K-Q	Si-NPN	-	3S	Rhm	→2SC2411K
2SC2411K-R	Si-NPN	-	3S	Rhm	→2SC2411K
2SC2412KLN	Si-NPN	=2SC2412:ra	3Sa	-	BC850,BCF81,2SC3323
2SC2412KLN-E	Si-NPN	-	3S	Rhm	→2SC2412KLN
2SC2412KLN-R	Si-NPN	-	3S	Rhm	→2SC2412KLN
2SC2412KLN-S	Si-NPN	-	3S	Rhm	→2SC2412KLN
2SC2412K-Q	Si-NPN	-	3S	Rhm	→2SC2412K
2SC2412K-R	Si-NPN	-	3S	Rhm	→2SC2412K
2SC2412K-S	Si-NPN	-	3S	Rhm	→2SC2412K
2SC2412L-LE	Si-NPN	-	?3S	Rhm	→2SC2412L
2SC2412L-LR	Si-NPN	-	?3S	Rhm	→2SC2412L
2SC2412L-LS	Si-NPN	-	?3S	Rhm	→2SC2412L
2SC2412LN	Si-NPN	=2SC2412:ra	?3Sd	-	-
2SC2413	Si-NPN	HF,40V,0,05A,300MHz	?3Sd	Rhm	(BFS17..18,BFS54,BF840..841)
2SC2413-AN	Si-NPN	-	?3S	Rhm	→2SC2413
2SC2413-AP	Si-NPN	-	?3S	Rhm	→2SC2413
2SC2413-AQ	Si-NPN	-	?3S	Rhm	→2SC2413
2SC2413K	Si-NPN	=2SC2413:	3Sa	-	BFS17..18,BFS54,BF840..841
2SC2413K-N	Si-NPN	-	3S	Rhm	→2SC1413K
2SC2413K-P	Si-NPN	-	3S	Rhm	→2SC2413K
2SC2413K-Q	Si-NPN	-	3S	Rhm	→2SC2413K
2SC2414	Si-NPN	Sw,Pow,500V,2A,70W,<1/3,5µS	23a$	Mat	BU126,BUX45..46,TIP54,2SC3083..
2SC2415	Si-NPN	=2SC2414:7A,90W	23a$	Mat	BU326,BU426,BUX45,2SC3041..
2SC2416	Si-NPN	=2SC2414:10A,120W	23a$	Mat	BUW25..26,BUW34..36,2SC3046..
2SC2417	Si-NPN	Min,UHF,-/10V,0,03A,0,25W,6,5GHz	24	Tos	BFQ57..58,BFQ65,BFQ74,2SC3276..
2SC2418	Si-NPN	Min,UHF,-/8V,0,08A,0,33W,7GHz	24	Tos	2SC2876,2SC3358,2SC3603
2SC2419	Si-NPN	VHF-Dr/Out,65V,1A,Pq>2,5W(175MHz)	2a*	Tos	BFS23,BLY34
2SC242	Si-NPN	=2SC240	23a$	Nec	BD245C,BDV93,BDX93,2N5758..60..
2SC2420	Si-NPN	VHF-Pow,40V,6A,Pq>32W(175MHz)	5Sr	Tos	2N6084
2SC2421	Si-NPN-Darl	AF,Sw-Pow,200V,5A,100W,30MHz,B=700	23a$	Fui	2SD776,2SD920..921,2SD929,2SD1090..
2SC2422	Si-NPN-Darl	=2SC1421:150V	23a$	Fui	2SD776,2SD920..923,2SD929,2SD1090..
2SC2423	Si-NPN-Darl	=2SC1421:40W	22a$	Fui	2SD930,2SD1023,2SD1025
2SC2424	Si-NPN-Darl	=2SC1421:150V,40W	22a$	Fui	2SD930,2SD1023,2SD1025,2SD1128..
2SC2425	Si-NPN	AF/Vid-Pow,300/200V,0,1A,20MHz	17j$	Fui	2SC1505,,1507,2SC1755..1758,2SC1905
2SC2426	Si-NPN	-		Fui	-
2SC2427	Si-NPN	Sw,Pow,500/400V,7A,40W,20MHz	17j$	Fui	MJE13006,2SC2335,2SC4055,2SC4106..
2SC2428	Si-NPN	Sw,Pow,Reg-Pow,180/180V,12A,120W,80MHz	23a$	Fujitsu	MJ15015,BDW14,BDY56,2SC2608..
2SC2429	Si-NPN	Sw,Pow,Reg-Pow,450/400V,15A,150W,30MHz	23a$	Fujitsu	BUV25,BUW44,BUX25,2SD641..
2SC2429A	Si-NPN	=2SC2429:600/450V	23a$	-	BUS13(A),BUW45..46,2SD641..
2SC243	Si-NPN	=2SC240:140V	23a$	Nec	BD245D,2N4347,2N5760,2SD731,2SD1046..
2SC2430	Si-NPN	Sw,Pow,120/120V,10A,100W,80MHz	23a$	Fui	2SC2706,2SC2837,2SC2987
2SC2431	Si-NPN	Sw,Pow,120/120V,15A,100W,80MHz	23a$	Fui	-
2SC2432	Si-NPN	Sw,Pow,70/70V,15A,100W,80MHz	23a$	Fui	2SC3256
2SC2433	Si-NPN	Sw,Pow,120/120V,30A,150W,80MHz	23a$	Fui	BUW39,BUX39,2N5671,2N6272
2SC2434	Si-NPN	=2SC2433:70/70V	23a$	Fui	BUW39,BUX39,2N6270,2N6272
2SC2435	Si-NPN-Darl	Sw,Pow,100/100V,10A,100W,B>2000	23a$	Fujitsu	BDX65B,BDX83C,MJ4035,2SD628..29..
2SC2436	Si-NPN-Darl	=2SC2435:15A	23a$	Fui	BDX67B,MJ4035,2SD729..
2SC2437	Si-NPN	Sw,Pow,450/400V,7A,100W	23a$	Fujitsu	BUX15,BUX44,TIP57A..58A,2SC3041..
2SC2438	Si-NPN	Sw,Pow,150/100V,7A,50W,<500/3000nS	17j$	Fjd	BU406..408,BUW64A..C,MJE15030..
2SC2439	Si-NPN	Sw,Pow,150/100V,7A,50W,<500/3000nS	17j$	Fjd	BU406..408,BUW64A..C,MJE15030..
2SC244	Si-NPN	=2SC240:60V	23a$	Nec	BD245A,BDV91,BDX91,2N4914..15..
2SC2440	Si-NPN	Sw,Pow,450/400V,5A,40W	17j$	Fjd	MJE53T,2SC2518,2SC2542,2SC3056..
2SC2441	Si-NPN	AF-Dr-Pow,180/160V,0,08A,150MHz	14h$	Sanyo	BF415,BF417,BF469,BF471,2SD1610+
2SC2442	Si-NPN	Sw,Pow,600V,30A,200W,<2/8µS	68a$	Fjd	2SC2204,2SC2977,2SD295,2SD644,.
2SC2443	Si-NPN	Sw,Pow,600V,50A,400W	?74	Fjd	-
2SC2444	Si-NPN	Sw,Pow,500/400V,30A,250W,<1,5/4µS	68a$	Tos	2SC1300,2SC1471,2SC1874,2SC2220..
2SC2445	Si-NPN	Sw,Pow,300/200V,30A,250W,<1/3µS	68a$	Tos	2SC1299,2SC1873,2SD542..543,2SD643,..
2SC2447	Si-NPN	UHF,20V,0,05A,0,25W,1600MHz	5g	Mat	BFR37,BFS55,BFW30,BFX73
2SC2448	Si-NPN	Sw,Pow,650/600V,7A,80W,<1/4µS	23a$	Fjd	BU526,BUX47,2SC3092,2SC3449..
2SC2449	Si-NPN	Sw,Pow,650/600V,7A,80W,<1/2,5µS	23a$	Fjd	BU526,BUX47,2SC3092,2SC3449..
2SC245	Si-NPN	=2SC240:120V	23a$	Nec	BD245C,2N5759..60,2SD718,2SD896..
2SC2450	Si-NPN	=2SC2448:750/700V	23a$	Fjd	BU526,BUX47,2SC3092,2SC3449..
2SC2451	Si-NPN	=2SC2449:750/700V	23a$	Fjd	BU526,BUX47,2SC3092,2SC3449..

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2SC2452	Si-NPN	=2SC2448: 850/800V	23a$	Fjd	BU526, BUX47, 2SD811, 2SC3636..
2SC2453	Si-NPN	=2SC2449: 850/800V	23a$	Fjd	BU526, BUX47, 2SD811, 2SC3636..
2SC2454	Si-NPN	VHF, TV-IF, 50V, 0,03A, 550MHz	25za	Mat	2SC2467, 2SC2727, 2SC2729
2SC2455	Si-NPN	VHF-Pre, 30V, 0,02A, >450MHz	25u	Mat	2SC2464, 2SC2466, 2SC2726, 2SC2728..
2SC2456	Si-NPN	Vid-Out, TV-HD-Dr, 300/300V, 0, 1A, 10W	14h$	Tos	BF417, BF459, 2SC3417, 2SC3503..
2SC2457	Si-NPN	-		Tos	-
2SC2458	Si-NPN	50V, 0.15A, 0.2W, 80MHz	-		-
2SC2458(L)	Si-NPN	GenP, LN, 50V, 0,15A, 0,2W, >80MHz	41c	Tos	BC184, BC414, BC550, 2SC2240..
2SC2459	Si-NPN	GenP, 120V, 0,1A, 0,2W, 100MHz	41c	Tos	2SC1845, 2SC2240, 2SC2389, 2SC3245(A),..
2SC246	Si-NPN	=2SC240: 180V	23a$	Nec	BD245E, BU608, 2SC2261..2262, 2SD751
2SC2460	Si-NPN	AF, Sw-Pow, 140/140V, 12A, 100W, 90MHz	23a$	Tos	BDW10, 2SD425, 2SD551, 2SD1047..
2SC2460A	Si-NPN	=2SC2460: 120W	23a$	-	BDW10, BDW14, 2SD424..425, 2SD551..
2SC2461	Si-NPN	AF, Sw-Pow, 150/150V, 15A, 150W	23a$	Tos	2SC1884..1585, 2SC2608, 2SD424..
2SC2461A	Si-NPN	=2SC2460: 160V	23a$	-	2SC1585..1586, 2SC2608, 2SD424..
2SC2462	Si-NPN	50V, 0,1A, 230MHz	35a	Hit	BC846..847, BCW71..72, BCW81..
2SC2462-B	Si-NPN	-	35	Hit	→2SC2462
2SC2462-C	Si-NPN	-	35	Hit	→2SC2462
2SC2462-D	Si-NPN	-	35	Hit	→2SC2462
2SC2463	Si-NPN	=2SC2462: 55V	35a	Hit	BC846, BCV71..72, 2SC3323..
2SC2463-D	Si-NPN	-	35	Hit	→2SC2463
2SC2463-E	Si-NPN	-	35	Hit	→2SC2463
2SC2463-F	Si-NPN	-	35	Hit	→2SC2463
2SC2464	Si-NPN	UHF-Pre-in, TV-Tuner, 30V, 20mA, 900MHz	25u	Hit	2SC2466, 2SC2144, 2SC2360, 2SC2726
2SC2465	Si-NPN	VHF-Pre, TV-Tuner, 20V, 20mA, 550MHz	25za	Hit	2SC2470, 2SC2368
2SC2466	Si-NPN	UHF-Mix, TV-Tuner, 30V, 50mA, 2,2GHz	25u	Hit	2SC2353, 2SC2728
2SC2467	Si-NPN	VHF-Mix, TV-Tuner, 30V, 50mA, 900MHz	25za	Hit	2SC2454, 2SC2727, 2SC2729
2SC2468	Si-NPN	VHF-Mix/Osc, TV-Tuner, 30V, 50mA, 900MHz	24b	Hit	BF362..363, BFW93
2SC2469	Si-NPN	VHF-Mix/Osc, TV-Tuner, 30V, 50mA, >600MHz	24b	Hit	BF362..363, BFW93
2SC247	Si-NPN	GenP, 100V, 0,1A, 0,6W, 150MHz	2a$	Fui	BF257..259, 2SC2240, 2SC3245(A)..
2SC2470	Si-NPN	VHF, 30V, 0,05A, 0,2W, 2,2GHz	25za	Hit	2SC2465, 2SC2368
2SC2471	Si-NPN	TV, UHF-0, 30V, 0,05A, 0,31W, 2GHz	7f	Hit	BF357, 2SC2570(A), 2SC3037
2SC2472	Si-NPN	UHF, LN, 30V, 0,05A, 0,3W, 2,2GHz	7f	Hit	BF357, 2SC2570(A), 2SC3037
2SC2473	Si-NPN	VHF, LN, 30V, 0,05A, 0,3W, 2,2GHz	7f	Hit	BF357, 2SC2570(A), 2SC3037
2SC2474	Si-NPN	Sw, 60V, 0,2A, 0,6W, <70/250nS	7e	Nec	BSV59, BSX49, 2N2221..22, 2N3903..04..
2SC2475	Si-NPN	Sw, 60V, 0,6A, 0,6W, <35/285nS	7e	Nec	BSV59, BSX49, 2N2221..22, 2N3301..02..
2SC2476	Si-NPN	Sw, 30V, 0,2A, 0,6W, <70/250nS	7e	Nec	BSW41, BSY63, 2N708, 2N914, 2N4123..
2SC2477	Si-NPN	Sw, 60V, 0,6A, 0,6W, <35/300nS	7e	Nec	BSX48, BSX87..88, BSX97, 2N914..
2SC248	Si-NPN	GenP, 70V, 0,05A, 0,3W, 170MHz	2a$	Fui	BC546, 2SC1775(A), 2SC1890(A), 2SD755..
2SC2480	Si-NPN	VHF/UHF, 30V, 50mA, 1300MHz	35a	Matsushita	BFS17, 2SC3005, 2SC3016, 2SC3161
2SC2480-S	Si-NPN	-	35	Mat	→2SC2480
2SC2480-T	Si-NPN	-	35	Mat	→2SC2480
2SC2481	Si-NPN	TV-VD, AF, Sw, Pow, 150V, 1,5A, 20W, >20MHz	14h$	Tos	2SC2690, 2SC3117, 2SD669
2SC2482	Si-NPN	Vid, TV-HD-Dr, 300/300V, 0, 1A, 0,9W	7c(9mm)	Tos	2SC3468, 2SC4166, (2SC3805, 2SC4019..)
2SC2483	Si-NPN	TV-AF-Pow, 160/160V, 1,5A, 15W, 120MHz	13j$	Toshiba	(2SC2238(A,B), 2SC2344, 2SC2529,..)
2SC2484	Si-NPN	AF, Sw-Pow, 80/80V, 5A, 60W, 15MHz	18j$	Mat	BD245B, 2SD718, 2SD895, 2SD1046..
2SC2485	Si-NPN	AF, Sw-Pow, 100/100V, 6A, 70W, 15MHz	18j$	Mat	BD245C, 2SD718, 2SD896, 2SD1046..
2SC2486	Si-NPN	AF, Sw-Pow, 120/120V, 7A, 80W, 15MHz	18j$	Mat	BD245C, 2SD718, 2SD896, 2SD1046..
2SC2487	Si-NPN	AF, Sw-Pow, 150/150V, 6A, 80W, 50MHz	23a$	Mat	2SC2837, 2SD551, 2SD732..733, 2SD1046,..
2SC2488	Si-NPN	AF, Sw-Pow, 150/150V, 8A, 100W, 50MHz	23a$	Mat	2SC2837, 2SD551, 2SD733, 2SD1047..
2SC2489	Si-NPN	AF, Sw-Pow, 150/150V, 10A, 120W, 50MHz	23a$	Mat	2SC2837, 2SD551, 2SD733, 2SD1047..
2SC249	Si-NPN	GenP, 70V, 0,07A, 0,5W, 170MHz	2a$	Fui	BC546, 2SC2631..32, 2SC3245(A)..
2SC2490	Si-NPN	UHF-Pow, 55V, 10A, Pq=75W(770MHz)	?57s*	Fui	-
2SC2491	Si-NPN	Hi-beta, Hi-Ueb, 100V, 6A, 50W, B=600	17j$	Sak	(2SC2316, 2SD1474)
2SC2492	Si-NPN	AF, Sw-Pow, 120/120V, 10A, 100W, 70MHz	23a$	Sak	2SC2837, 2SD551, 2SD733, 2SD1047..
2SC2493	Si-NPN	=2SC2482: 150/150V	23a$	Sak	2SC2837, 2SD551, 2SD733, 2SD1047..
2SC2494(K)	Si-NPN	UHF-Dr/Out, 25V, 0,75A, Pq>1,4W(500MHz)	58r*	Nec	-
2SC2494M	Si-NPN	=2SC2494:	?58r*	-	-
2SC2495(K)	Si-NPN	UHF-Pow, 25V, 1,5A, Pq>3,2W(500MHz)	58r*	Nec	-
2SC2495M	Si-NPN	=2SC2495:	?58r	-	-
2SC2496(A)	Si-NPN	UHF-Pow, 35V, 10A, Pq=37W(500MHz)	57s	Nec	BLU45/12, MRF646, MRF648, 2SC2783
2SC2497	Si-NPN	70V, 1.5A, 5W, 150MHz	-		-
2SC2497(A)	Si-NPN	AF, Sw-Pow, 70V, 1,5A, 5W, 150MHz	14h$	Mat	BD139, BD377, 2SC2690, 2SD1177..78..
2SC2498	Si-NPN	VHF/UHF, LN, 30V, 0,05A, 0,3W, 3,5GHz	7f	Tos	2SC2570(A), 2SC3037, 2SC3512
2SC2499	Si-NPN	VHF/UHF, LN, 20V, 0,03A, 0,3W, 4GHz	7f	Tos	2SC2570(A), 2SC3037, 2SC3512

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2SC25	Si-NPN	GenP,60V,0,06A,0,5W	2a	Mat	BC174,BC182,BC190,BC546,2N2218..
2SC250	Si-NPN	HF,20V,25mA,0,06W,170MHz	4g	Fui	BF240..241,BF254..255,BF594..595,..
2SC2500	Si-NPN	Lo-sat,30V,2A,0,9W,150MHz	7c(9mm)	Tos	2SC3328,2SD1146,2SD1207,2SD1247..
2SC2501	Si-NPN	Sw,Pow,500/400V,3A,40W,20MHz	17j$	Shi	BUT93,TIP75C,2SC3038,2SC4105..
2SC2502	Si-NPN	Sw,Pow,500/400V,6A,50W,20MHz	17j$	Shi	MJE13006,2SC2335,2SC3039,2SC4106..
2SC2503	Si-NPN	Sw,Pow,500/400V,8A,80W,20MHz	?20j$	Shi	-
2SC2504	Si-NPN	Sw,Pow,500/400V,10A,100W,20MHz	?20j$	Shi	-
2SC2505	Si-NPN	Sw,Pow,500/400V,3A,60W,20MHz	22a$	Shi	BUT93,TIP75C,2SC2826,2SC3038..
2SC2506	Si-NPN	Sw,Pow,500/400V,6A,60W,20MHz	22a$	Shi	MJE13006,2SC3039,2SC3170,2SC4106..
2SC2507	Si-NPN	Sw,Pow,500/400V,20A,200W,20MHz	23a$	Shidengen	BUS14(A),2SC2930,2SC3058,2SC3085..
2SC2508	Si-NPN	VHF-Pow,40V,6A,Pq>27W(175MHz)	59r	Tos	MRF224
2SC2509	Si-NPN	AM-Pow,40V,5A,Pep=10W(28MHz)	17k*	Tos	-
2SC251(A)	Si-NPN	VHF/UHF,30V,30mA,900MHz	5g	Nec	BF180..183,BF689,BF763,2N2857..
2SC2510	Si-NPN	AM-Pow,55V,20A,Pep>150W(28MHz)	59r	Tos	-
2SC2511	Si-NPN	FM,60V,0,1A,150MHz	7f	Hit	BF240..241,BF254..255,BF959..
2SC2512	Si-NPN	VHF-Mix,TV-Tuner,30V,50mA,900MHz	7f	Hit	BF377..378,BF689K,BF763,2N2857..
2SC2516	Si-NPN	150V,5A,30W,<0.5/2µS	-		-
2SC2516(A)	Si-NPN	AF,Sw-Pow,150V,5A,30W,<0,5/3µS	17j$	Nec	BD243D,2SD772(A,B)
2SC2517	Si-NPN	=2SC2516:<500/2500nS	17j$	Nec	BD243D,2SD772(A,B)
2SC2518	Si-NPN	Sw,Pow,500/400V,5A,40W,<1000/3200nS	17j$	Nec	MJE13070,2SC2535,2SC2827,2SC3830..
2SC2519	Si-NPN	GenP,30V,0,03A,0,25W,230MHz	9b	Matsushita	BF240..241,BF254..255,BF594..595,..
2SC252	Si-NPN	VHF/UHF,30V,30mA,900MHz	5g	Nec	BF180..183,BF689,BF763,2N2857..
2SC2520..2521	Si-NPN	-		Fui	-
2SC2522	Si-NPN	AF,Sw-Pow,120/120V,12A,120W,80MHz	23a$	Fui	2SC2987(A),2SD425,2SD551,2SD1047..
2SC2522A	Si-NPN	=2SC2522:150V	23a$	-	2SC2987A,2SD733,2SD551,2SD1047..
2SC2523	Si-NPN	=2SC2522:160V	23a$	Fui	2SC2987A,2SD733,2SD551,2SD1047..
2SC2524	Si-NPN	AF,Sw-Pow,160/160V,15A,150W,80MHz	23a$	-	MJ15015,2SC1585..86,2SC2608,2SD424..
2SC2525	Si-NPN	=2SC2522:	20j$	Fui	2SC2564..2565,2SC2766(A),2SC2921..
2SC2526	Si-NPN	=2SC2523:	20j$	Fui	2SC2565,2SC2766(A),2SC2921..22..
2SC2527	Si-NPN	DC-DC Converter,120V,10A,60W,80MHz	17j$	Fui	-
2SC2528	Si-NPN	AF,Sw-Pow,120V,2A,25W,160MHz	17j$	Fui	2SC2660,2SD759..760
2SC2529	Si-NPN	=2SC2528:160V	17j$	Fui	2SC2660,2SD759..760
2SC253	Si-NPN	VHF/UHF,30V,30mA,900MHz	5g	Nec	BF180..183,BF689,BF763,2N2857..
2SC2530	Si-NPN	AF,Sw-Pow,40V,0,5A,20W,35MHz	17j$	Fui	BD239,2SC1398
2SC2531	Si-NPN	Min,UHF-LN,25V,0,03A,2,5GHz	24	Tos	BFR34,BFT97,BFW93
2SC2532	Si-N-Darl+Di	40V,0,3A,B>5000	35	Tos	BCV27,2SD1383K
2SC2533	Si-NPN	-		Tos	-
2SC2534	Si-NPN	Sw,Pow,500/400V,2A,20W,-/<3,5µS	17j$	Tos	BUV36,BUX84..85,2SC2333,2SC2738..
2SC2535	Si-NPN	=2SC2534:5A,40W	17j$	Tos	BUT56(A),TIP75C,2SC2827,2SC3038..
2SC2536	Si-NPN	=2SC2534:7A,80W	18j$	Tos	BU426(A),BUP22,TIP58A,2SC3040,..
2SC2537	Si-NPN	Sw,Pow,410V,10A,100W,-/3050nS	18j$	Mit	BUV47(A),BUW12(A),2SC2625,2SC3042..
2SC2538	Si-NPN	VHF-Osc/Dr,40V,0,4A,Pq=0,6W(175MHz)	7b	Mit	BFS51,BFX55,BLW16,MRF607..
2SC2539	Si-NPN	VHF-Pow,35V,4A,Pq=17W(175MHz)	58s*	Mit	-
2SC254	Si-NPN	GenP,50V,0,8A,0,65W,250MHz	2a$	Oki	BC140..141,BC300..302,2N3053..
2SC2540	Si-NPN	VHF-Pow,35V,10A,Pq=45W(175MHz)	57s*	Mit	BLV45/12
2SC2541	Si-NPN	Sw,Pow,500/450V,10A,100W,16MHz	18j$	Mit	BUV47(A),BUW12(A),2SC2740,2SC3042..
2SC2542	Si-NPN	Sw,Pow,450V,5A,40W,<1/3µS	17j$	Fjd	BUT56(A),MJE53T,2SC2440,2SC3056..
2SC2543	Si-NPN	GenP,90/90V,0,1A,0,4W,90MHz	7c	Hit	2SC2240,2SC2363,2SC2459,2SC3245(A),..
2SC2544	Si-NPN	GenP,120/120V,0,1A,0,4W,90MHz	7c	Hit	2SC2240,2SC2363,2SC2459,2SC3245(A),..
2SC2545	Si-NPN	=2SC2543:ra,60V	7c	Hit	BC414,BC550,2SC2240,2SC2459..
2SC2546	Si-NPN	=2SC2543:ra	7c	Hit	2SC2240,2SC2363,2SC2389,2SC2459..
2SC2547	Si-NPN	=2SC2543:ra,120/120V	7c	Hit	2SC2240,2SC2363,2SC2389,2SC2459..
2SC2548	Si-NPN	VHF/UHF,LN,20V,0,03A,0,25W,4GHz	7f	Tos	2SC2499,2SC2570(A),2SC3037
2SC2549	Si-NPN	UHF,LN,15V,0,03A	7f	Son	BF630,2SC2499,2SC2570(A),2SC2548
2SC255	Si-NPN	=2SC254:80V	2a$	Oki	BC140..141,BC300..301,2N1990..
2SC2550	Si-NPN	HF/Sw,60V,0,2A,0,3W,250MHz	2a$	Tos	BC182,BC546,2N2221..2222(A)..
2SC2551	Si-NPN	Vid,300V,0,1A,0,4W,80MHz	7c	Tos	BF299,BF393,BF420A,2SC3468..
2SC2552	Si-NPN	Sw,Pow,500/400V,2A,20W,-/<3,5µS	17j$	Tos	BUV36,BUX84..85,2SC2333,2SC2738..
2SC2553	Si-NPN	=2SC2552:5A,40W	17j$	Tos	MJE13070,TIP75C,2SC2827,2SC3830..
2SC2555	Si-NPN	=2SC2552:8A,80W	18j$	Tos	BU426(A),TIP58A,2SC3040,2SC4106..
2SC2556	Si-NPN	AF/Vid-Out,130/40V,1A,200MHz	14h$	Mat	2SC2690A,2SC3117,2SD669
2SC2556A	Si-NPN	=2SC2556:180/50V	14h$	-	2SC3117,2SD669
2SC2557	Si-NPN	GenP,LN,60V,0,05A,0,25W,220MHz	7c	Mat	BC414,BC550,2SC2240,2SC2459..
2SC2558	Si-NPN	UHF-Dr/Out,35V,0,5A,Pq=1,3W(860MHz)	58r*	Nec	-

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2SC2559	Si-NPN	UHF-Pow,35V,1,5A,Pq=6W(860MHz)	58r*	Nec	2SC2685
2SC256	Si-NPN	=2SC254:90V	2a$	Oki	BC141,BC300..301,2N1990,2N2102..
2SC2560	Si-NPN	UHF-Pow,35V,3A,Pq=11W(860MHz)	58r*	Nec	2SC2850
2SC2561	Si-NPN	GenP,HF,30V,0,03A,0,25W,250MHz	9b	Matsushita	BF240..241,BF254..255,BFS94..595..
2SC2562	Si-NPN	Lo-sat,60V,5A,25W,120MHz	17j$	Tos	2SC3253..3255,2SC3258,2SD1235
2SC2563	Si-NPN	AF,Sw-Pow,120/120V,8A,80W,90MHz	18j$	Tos	2SC2706,2SC2837,2SC2987(A)
2SC2564	Si-NPN	AF,Sw-Pow,140/140V,12A,120W,90MHz	20j$	Tos	2SC2526,2SC2766,2SC2838,2SC2921..
2SC2565	Si-NPN	=2SC2564:160/160V,15A,150W	20j$	Tos	2SC2526,2SC2766(A),2SC2921..2922..
2SC2566	Si-NPN	VHF,30V,15mA,650MHz	9b	Matsushita	BF314,BF502,BF505,BF507,BF959..
2SC2567	Si-NPN	35V,0,05A,320MHz	?35a	Mat	BC846..848,BCW31..33,BCW71..72..
2SC2567A	Si-NPN	=2SC2567:55V	?35a	-	BC846..847,BCW71..72,BCW81..
2SC2568	Si-NPN	Vid-Pow,300/300V,0,2A,10W,80MHz	14h$	Nec	BF417,BF459,2SC3417,2SC3503..
2SC2569	Si-NPN	AF,Sw-Pow,150/150V,6A,40W,<1/3µS	22a$	Fjd	BU409,BUW64,MJE15030,2SC2334..
2SC257	Si-NPN	=2SC254:0,8W	2a$o	Oki	→2SC254
2SC2570(A)	Si-NPN	UHF,25V,0,07A,5GHz	7f	Nec	2SC3037,2SC3512
2SC2570A	Si-NPN	25V,70mA,0.6W	-		-
2SC2571(-1,-2)	Si-NPN	AF,Sw-Pow,100..130V,10A,95W,80MHz	-	Son	-
2SC2572	Si-NPN	Sw,60V,0,2A,0,36W,<80/420nS	2a$	Nec	BSV59,BSX49,2N2222(A),2N3904..
2SC2573..2574	Si-NPN	-		Mit	-
2SC2575	Si-NPN	GenP,50V,0,2A,0,3W,200MHz	7b	Mit	BC167,BC182,BC237,BC547,2SD767..
2SC2575L	Si-NPN	=2SC2575:ra	7b	-	BC414,BC550,2SC2240,2SC2459..
2SC2576	Si-NPN	-		Mit	-
2SC2577	Si-NPN	AF,Sw-Pow,120/80V,6A,60W,20MHz	18j$	Sak	BD245C,2SC2706,2SC2837,2SC2987(A),..
2SC2578	Si-NPN	=2SC2577:140/140V,7A,70W	18j$	Sak	BD245D,2SC2706,2SC2987(A),2SD1046,..
2SC2579	Si-NPN	=2SC2577:160/160V,8A,80W,-/3,1µS	18j$	Sak	BD245D,2SC2987A,2SC3263,2SD1047..
2SC258	Si-NPN	=2SC255:0,8W	2a$o	Oki	→2SC255
2SC2580	Si-NPN	=2SC2577:180/120V,9A,90W	18j$	Sak	BD245E,2SC3263,2SC3855,2SD751..
2SC2581	Si-NPN	=2SC2577:200/140V,10A,100W,-/2,8µS	18j$	Sak	BD245F,2SC3263,2SC3855
2SC2582	Si-NPN	AF/HF/Sw-Pow,45V,1A,10W,200MHz	14h$	Mat	BD135,BD226,BD375,2SD1378..
2SC2583	Si-NPN	-		Nec	-
2SC2584	Si-NPN	VHF-Pow,45V,4A,Pq=22W(175MHz)	58r*	Nec	2SC2094
2SC2585	Si-NPN	UHF,LN,24V,0,4W,0,065A,8,5GHz	51s	Nec	BFG195,BFQ82,2SC3358,2SC3603
2SC2586	Si-NPN	UHF-Dr/Out,35V,0,4A,Pq=1,6W(500MHz)	2e*	Nec	(BFS50,MRF629,2SC2762,2SC3185..)
2SC2587(A)	Si-NPN	AF,Sw-Pow,150V,10A,120W,70MHz	20j$	Nec	2SC2526,2SC2565,2SC2838,2SD745A,B..
2SC2588(A)	Si-NPN	AF,Sw-Pow,150V,12A,120W,60MHz	20j$	Nec	2SC2526,2SC2564..2565,2SC2838..
2SC2589	Si-NPN	AF,Sw-Pow,180/180V,10A,200W,60MHz	23a$	Nec	BDW16,2SC1585..86,2SC2607..08..
2SC259	Si-NPN	=2SC256:0,8W	2a$o	Oki	→2SC256
2SC2590	Si-NPN	AF,Sw-Pow,120/120V,0,5A,5W,200MHz	14h$	Mat	2SC2690(A),2SD1382,2SD1563
2SC2591	Si-NPN	AF,Sw-Pow,150/150V,1A,20W,200MHz	17j$	Mat	2SC1913(A),2SC2238(A,B),2SC2344..
2SC2592	Si-NPN	=2SC2591:180/180V	17j$	Mat	2SC1913A,2SC2238A,B,2SC2344,2SC2660
2SC2593	Si-NPN	Sym,20/20/20V,0,05A,0,14W	7c	Son	-
2SC2594	Si-NPN	AF,Sw-Pow,40V,5A,10W,150MHz	14h$	Mat	,MJE200,2SC3420,2SD741,2SD826..
2SC2595	Si-NPN	UHF-Pow,36V,1,2A(ss),Pq=0,9W(840MHz)	51r	Mat	-
2SC2596	Si-NPN	UHF-Pow,36V,4A(ss),Pq=3,5W(840MHz)	51r	Mat	-
2SC2597	Si-NPN	UHF-Pow,36V,6A,Pq=9W(840MHz)	51r	Mat	-
2SC2598	Si-NPN	Dual,UHF,20V,0,07A,5GHz	-	Fui	-
2SC2599	Si-NPN	UHF,LN,20V,0,02A,0,2W	52r	Fui	BFG90,BFQ28,BFQ60,BFQ71,BFR49
2SC26	Si-NPN	GenP,60V,0,1A,0,5W,150MHz	37a$	Fui	BC174,BC182,BC190,BC546,2N2219..
2SC260	Si-NPN	HF-Pow,30V,1A,280MHz	2a$	Oki	(BD135,BD226,2SC3419,2SD1200,..)
2SC2600	Si-NPN	UHF,25V,0,04A,0,35W,6GHz	52r	Fui	BFQ57..58,BFQ74,2SC1655..1656..
2SC2601	Si-NPN	Dual,70V,0,2A,0,4W,100MHz	7-SIP/bp4	Mit	-
2SC2602	Si-NPN	GenP,LN,MC-Cartridge,70V,0,2A,0,5W	7b	Mit	2SC2240,2SC2459,2SC2674..2675..
2SC2603	Si-NPN	GenP,50V,0,2A,0,3W,200MHz	41c	Mit	BC167,BC182,BC237,BC547,2SD767..
2SC2604	Si-NPN	GenP,LN,30V,0,1A,0,2W,230MHz	7c	Hit	BC169,BC184,BC239,BC549,2SC2240+
2SC2605	Si-NPN	=2SC2604:50V	7c	Hit	BC184,BC413..414,BC550,2SC2240..
2SC2606	Si-NPN	Vid-Pow,300/300V,0,05A,30MHz	?17j$	Son	2SC1505..1507,2SC1755..1757,2SC1905,..
2SC2607	Si-NPN	Sw,Pow,200/200V,15A,150W,20MHz	23a$	Sanken	MJ15015,BDW16,2SD665,2SD753..
2SC2608	Si-NPN	=2SC2607:17A,200W	23a$	Sak	BUV11,BUW58,BUX11,2SC2865(A)
2SC2609	Si-NPN	VHF-Pow,55V,15A,Pq=110W(220MHz)	57s*	Mit	2SC2897
2SC261	Si-NPN	=2SC260:60V	2a$	Oki	(BD137,BD228,2SD1200,2SD1378,..)
2SC2610	Si-NPN	Vid,300V,0,1A,0,8W,80MHz	7c(9mm)	Hit	BF299,BF393,BF420A,2SC3468..69..
2SC2611	Si-NPN	=2SC2610:	14h$	Hit	BF417,BF459,2SC3417,2SC3503..
2SC2612	Si-NPN	Sw,Pow,500/400V,3A,30W	17j$	Hit	BUT93,TIP75C,2SC2826,2SC3038..
2SC2613(K)	Si-NPN	=2SC2612:5A,40W	17j$	-	BUT56(A),2SC2535,2SC2827,2SC3497..

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2SC2614	Si-NPN	=2SC2612:5A,60W	20j$	Hit	-
2SC2615	Si-NPN	=2SC2612:8A,80W	20j$	Hit	2SC2650,2SC2818
2SC2616	Si-NPN	=2SC2612:10A,100W	23a$	Hit	BUW25..26,BUW34..36,2SC3043..
2SC2617	Si-NPN	=2SC2612:15A,125W	23a$	Hit	BUV25,BUW44,BUX25,2SD641..
2SC2618	Si-NPN	GenP,35V,0,5A,50MHz	35a	Hitachi	BC817,BCX19,2SC3325,2SC3341..
2SC2618-B	Si-NPN	-	3S	Hit	→2SC2618
2SC2618-C	Si-NPN	-	3S	Hit	→2SC2618
2SC2618-D	Si-NPN	-	3S	Hit	→2SC2618
2SC2619	Si-NPN	GenP,30V,0,1A,230MHz	35a	Hitachi	BC846..848,BCW31..33,BCW71..72..
2SC2619-A	Si-NPN	-	3S	Hit	→2SC2619
2SC2619-B	Si-NPN	-	3S	Hit	→2SC2619
2SC2619-C	Si-NPN	-	3S	Hit	→2SC2619
2SC262	Si-NPN	=2SC260:80V	2a$	Oki	(BD139,BD230,2SD1200,2SD1378,..)
2SC2620	Si-NPN	VHF,30V,0,02A,940MHz	35a	Hit	BFS17,2SC3005,2SC3016,2SC3161
2SC2620-A	Si-NPN	-	3S	Hit	→2SC2620
2SC2620-B	Si-NPN	-	3S	Hit	→2SC2620
2SC2620-C	Si-NPN	-	3S	Hit	→2SC2620
2SC2621	Si-NPN	Vid,300/300V,0,2A,10W,>50MHz	14h$	Fui,Say	BF417,BF459,MJE3440,2SC3503..
2SC2621E	Si-NPN	300V,0.2A,10W,>50MHz	-		-
2SC2623	Si-NPN	Sw,Pow,450/400V,20A,100W,<1/4µS	23a$	Fujitsu	BUV24,BUX24,2SC3085,2SC3850..
2SC2624	Si-NPN	Sw,Pow,450/400V,5A,80W,<1/3µS	18j$	Fjd	BU426(A),TIP57A..58A,2SC3083..
2SC2625	Si-NPN	=2SC2624:10A	18j$	Fjd	2SC2541,2SC2740,2SC2789,2SC4138..
2SC2626	Si-NPN	=2SC2624:400/300V,15A,<0,8/2,8µS	18j$	Fjd	2SC2307,2SC3520,2SC3451,2SC4139..
2SC2627	Si-NPN	VHF-Pow,35V,2A,Pq=6W(175MHz)	?5Ss	Mit	BLW18,BLY62,2SC2281
2SC2628	Si-NPN	VHF-Pow,35V,4A,Pq=18W(175MHz)	?5Ss	Mit	BLY89,MRF209,2N5591,2N6082..
2SC2629	Si-NPN	VHF-Pow,35V,8A,Pq=34W(175MHz)	?5Ss	Mit	2N6084
2SC263	Si-NPN	Min,HF/Sw,15V,0,12A,0,1W,200MHz	24c	Oki	(BSX27,BSX92..93,2N2368..69(A),..)
2SC2630	Si-NPN	VHF-Pow,35V,14A,Pq=60W(175MHz)	57s*	Mit	BLV75/12,2SC3147
2SC2631	Si-NPN	GenP,LN,150V,0,05A,0,75W,160MHz	7c	Mat	2SC3800
2SC2632	Si-NPN	=2SC2631:1W	7c(9mm)	Mat	2SC3800
2SC2633	Si-NPN	=2SC2631:	17j$	Mat	2SC3514
2SC2634	Si-NPN	60V,0.1A,0.4W,200MHz	-		-
2SC2634(NC)	Si-NPN	GenP,LN,60V,0,1A,0,4W,200MHz	7c	Mat	BC550,2SC2240,2SC2389..90,2SC2459,..
2SC2635(H)	Si-NPN	Sw,650/600V,0,1A,0,75W,15MHz	2a$	Hit	2N5012..15,2SC1762,2SD594
2SC2636	Si-NPN	UHF,30V,0,05A,0,4W,1200MHz	9c	Mat	BF357,BF377..378,2SC2570(A),2SC3037
2SC2637	Si-NPN	Vid-Out,300/300V,0,1A,15W,100MHz	13j$	Matsushita	(BF617,BF758..759,MPSU10,..)
2SC2638	Si-NPN	VHF-Pow,35V,2A,Pq>6W(175MHz)	58s	Tos	-
2SC2639	Si-NPN	VHF-Pow,35V,3,5A,Pq>15W(175MHz)	58s	Tos	2SC2094
2SC264	Si-NPN	=2SC263:30V,400MHz,27/40nS	24c	Oki	(BSX92..93,2N2368..69(A),2N3011,..)
2SC2640	Si-NPN	VHF-Pow,35V,6A,Pq>28W(175MHz)	58s	Tos	-
2SC2641	Si-NPN	UHF-Pow,35V,1,4A,Pq>6W(470MHz)	58s	Tos	MRF641,2SC2284
2SC2642	Si-NPN	UHF-Pow,35V,2,8A,Pq>12W(470MHz)	58s	Tos	-
2SC2643	Si-NPN	UHF-Pow,35V,6A,Pq>25W(470MHz)	58s	Tos	-
2SC2644	Si-NPN	UHF,25V,0,12A,0,5W,4GHz	7f	Tos	2SC3337,2SC3779
2SC2645	Si-NPN	VHF/UHF,30V,0,05A,0,2W,1200MHz	24b	Mat	BF362,BF363
2SC2646	Si-NPN	VHF/UHF,30V,0,05A,0,2W,1200MHz	9b	Matsushita	BF377..378,BF689K,BF763,2N2857..
2SC2647	Si-NPN	AM/FM,30V,0,03A,0,4W,230MHz	9c	Mat	BF240..241,BF254..255,BF594..595,..
2SC2648	Si-NPN	UHF-Pow,35V,3,5A,Pq=17W(470MHz)	55r	Tos	BLX69,2SC1404
2SC2649	Si-NPN	UHF-Pow,35V,6A,Pq=22W(470MHz)	55r	Tos	2SC1339,2SC2173
2SC265	Si-NPN	=2SC263:40V	24c	Oki	(BSS11,BSX92..93,2N2368..69(A),..)
2SC2650	Si-NPN	Sw,Pow,500/400V,10A,100W,-/<3,5µS	20j$	Tos	2SC2818
2SC2651	Si-NPN	AM-Pow,45V,25A,Pep=90W(28MHz)	59r	Tos	2SC2879
2SC2652	Si-NPN	AM-Pow,85V,20A,Pep=220W(28MHz)	59r	Tos	-
2SC2653	Si-NPN	Vid-Pow,TV-VD,350V,0,2A,15W,>50MHz	13j$	Matsushita	BF759
2SC2653(H)	Si-NPN	=2SC2653:400/300V	13j$	Mat	-
2SC2654	Si-NPN	AF,Sw-Pow,40V,7A,40W,<1/3,5µS	17j$	Nec	BD243,BD543,BD795,2SD1442..
2SC2655	Si-NPN	AF,Sw,60V,2A,0,9W,100MHz	7c(9mm)	Tos	2SC3328,2SC3669,2SD1207,2SD2177..
2SC2656	Si-NPN	Sw,Pow,450/450V,7A,80W,<1,5/4,5µS	18j$	Fjd	BUP22,TIP57A..58A,2SC2788,2SC3040..
2SC2657	Si-NPN	Sw,Pow,800/500V,1,5A,70W,2,5MHz	23a$	Mat	BUX46(A),2SC3091,2SC3151,2SC3533..
2SC2657A	Si-NPN	=2SC2657:900/500V	23a$	-	BUX46A,2SC3155,2SC3151,2SC3533..
2SC2658	Si-NPN	Sw,Pow,800/500V,5A,90W,3MHz,<1/4µS	23a$	Mat	BU426(A),BUW11(A),BUX46(A),BUX82
2SC2658A	Si-NPN	=2SC2658:900/500V,<1,2/4,2µS	23a$	-	BU426A,BUW11A,BUX46A,BUX83..
2SC2659	Si-NPN	Sw,Pow,800/500V,7A,120W,3,5MHz	23a$	Mat	BU546,BUS12(A),BUW35..36,BUX81,..
2SC2659A	Si-NPN	=2SC2659:900/500V	23a$	-	BU546,BUS12A,BUW36,BUX81..

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2SC266	Si-NPN	AF/HF,30V,0,03A,0,1W,250MHz	24b	Nec	BC168,BC183,BC238,BC548,2SD767..
2SC2660	Si-NPN	200V,2A,30W,30MHz	-		-
2SC2660(A)	Si-NPN	AF,Sw-Pow,TV-VD,200V,2A,30W,30MHz	17j$	Mat	2SD386..387(A),2SD760,2SD772A,2SD1138
2SC2662	Si-NPN	AF/HF/Sw,100V,3A,8W(Tc=25°),50MHz	2a$	Tos	BSX64,2N4239,2SC696(A),2SC2214..
2SC2663	Si-NPN	-		Tos	-
2SC2664	Si-NPN	Sw,Pow,100/60V,3A,10W,50MHz	43a$	Tos	(BD791,BDX35..37,MJE243..244..)
2SC2665	Si-NPN	AF,Sw-Pow,100V,4A,55W,10MHz	18j$	Sak	BD245C,BDV95,2SD718,2SD895..896..
2SC2666	Si-NPN	VHF-Pow,35V,3,5A,Pq=7W(270MHz)	55r	Tos	BLW15,BLW81,2SC2106
2SC2667	Si-NPN	VHF-Pow,35V,6A,Pq=20W(270MHz)	55r	Tos	2SC2173
2SC2668	Si-NPN	FM-Preamp,40V,20mA,0,1W,550MHz	41c	Tos	BF255,BF314,BF495,BF502,BF595..
2SC2669	Si-NPN	AM/FM-IF,35V,50mA,0,2W,>100MHz	41c	Tos	BF240,BF254,BF494,BF594,2SC829..
2SC267	Si-NPN	AF-Pow,35V,0,2A,0,15W,90MHz	24b	Nec	BC168,BC183,BC238,BC548,2SD767..
2SC2670	Si-NPN	HF,AM,LN,35V,0,1A,0,2W,>80MHz	41c	Tos	BF240..241,BF254..255,BF594..595,..
2SC2671	Si-NPN	15V,80mA,0.6W,5.5GHz	-		-
2SC2671(F)	Si-NPN	UHF,15V,80mA,5,5GHz	7f	Mat	2SC2570(A),2SC3037,2SC3337
2SC2671(H)	Si-NPN	UHF,25V,70mA,4,5GHz	7f	Mat	2SC2570(A),2SC3037,2SC3337
2SC2672	Si-NPN	UHF,30V,0,05A,0,25W,3GHz	51s	Nec	BFQ72
2SC2673	Si-NPN	AF-Dr/Out,40V,1A,0,6W,150MHz	9c	Rhm	BC337,BC635,2SD1225,2SD1616..
2SC2674	Si-NPN	=2SC2675:120/120V	7c	Rhm	2SC2240,2SC2459,2SC3245,2SC3378..
2SC2675	Si-NPN	AF,LN,MM-/MC-Catridge,80V,0,1A	7c	Rhm	2SC2240,2SC2459,2SC2602
2SC2676(1)	Si-NPN	AF,LN,80V,0,01A,0,6W,200MHz	9b	NEC	2SC1775(A),2SC2240,2SC2389..2390..
2SC2677	Si-NPN	GenP,30V0,1A,0,625W,230MHz	7e	Hit	BC238,BC548,BF240..41,BF254..55..
2SC2678	Si-NPN	GenP,20V,0,03A,0,5W,300MHz	7e	Hit	BC238,BC548,BF240..41,BF254..55..
2SC2679	Si-NPN	UHF-Osc,30V,0,05A,Pq=8mW(930MHz)	7e	Hit	BF357,BF377..378,2SC2570(A),2SC3037
2SC267A	Si-NPN	=2SC267:50V	24b	-	BC167,BC182,BC237,BC547,2SD767..
2SC268	Si-NPN	Nix,Sw,60V,0,03A,0,15W,150MHz	24b	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC2680	Si-NPN	TV-IF,40V,0,03A,550MHz	35a	Mat	BF599,BF799,2SC3053,2SC3374..
2SC2681	Si-NPN	AF/HF-Pow,115/115V,10A,100W,80MHz	16j$	Nec	2SC2706,2SC2837,2SC2987,(BD245C,..)
2SC2682	Si-NPN	AF-Dr-Pow,180/180V,0,1A,8W,200MHz	14h$	Nec	BF415,BF458..459,2SC3416,2SD1610,..
2SC2683	Si-NPN	-		Mat	-
2SC2684	Si-NPN	UHF-A/Dr,36V,0,6A,Pq=0,95W(940MHz)	51r*	Mat	-
2SC2685	Si-NPN	UHF-A/Dr,36V,2A,Pq=5,5W(940MHz)	58v&	Mat	-
2SC2686	Si-NPN	UHF-Pow,36V,3A,Pq=13W(940MHz)	58v&	Mat	-
2SC2687	Si-NPN	AF/Vid,300/300V,0,2A,0,8W,80MHz	9b	NEC	BF299,BF420A,BF393,2SC3468..
2SC2688	Si-NPN	Vid-Pow,300/300V,0,2A,10W,80MHz	14h$	Nec	BF417,BF459,2SC3417,2SC3503
2SC2689	Si-NPN	AF/Vid-Pow,300/300V,0,2A,10W,80MHz	13j$	NEC	(BF382,BF617,BF859,MPSU10,..)
2SC268A	Si-NPN	=2SC268:80V	24b	-	BC546,BF297..299,BF422,BSS38..
2SC268B	Si-NPN	=2SC268:150V	24b	-	BF297..299,BF422,BFR87,2SC3467..
2SC269	Si-NPN	Sw,25V,0,2A,0,15W,400MHz,14/25nS	24b	Nec	BSS11..12,BSX19..20,2N2368..69(A),..
2SC2690	Si-NPN	AF/HF-Pow,120/120V,1,2A,20W,155MHz	14h$	Nec	2SC3117,2SD669,2SD1563(A)
2SC2690A	Si-NPN	=2SC2690:160/160V	14h$	-	2SC3117,2SD669,2SD1563A
2SC2691	Si-NPN	GenP,20V,0,05A,0,2W,100MHz	7b	Mit	BC168,BC183,BC238,BC548,2SC1890+
2SC2692	Si-NPN	UHF-Dr/Out,28V,0,2A,Pq=0,45W(2GHz)	?55s	Nec	BFQ68,BFT98
2SC2693	Si-NPN	AM-Pow,70V,5A,Pep=12W(28MHz)	59r	Tos	-
2SC2694	Si-NPN	VHF-Pow,35V,20A,Pq=75W(175MHz)	57s*	Mit	MRF244,2SC2782
2SC2695	Si-NPN	UHF-Pow,35V,10A,Pq=32W(520MHz)	58s*	Mit	-
2SC27	Si-NPN	HF,60V,0,1A,0,65W,350MHz	2a$	Fui	BFW16..17,BFX55,2N3725,2SC1385..
2SC270	Si-NPN	Sw,Pow,270V,5A,50W,22MHz	23a$	Sony	BU606..608,BUX16A..C,2SD1154..
2SC2700	Si-NPN	UHF-Pow,45V,1A,Pq=6,5W(470MHz)	55r	Fui	BLX93,2SC1040
2SC2701	Si-NPN	UHF-Dr/Out,35V,0,3A,Pq=1,1W(2,3GHz)	62d*	Fui	-
2SC2702	Si-NPN	UHF-Dr/Out,35V,0,5A,Pq=2,2W(2,3GHz)	62d*	Fui	-
2SC2703	Si-NPN	GenP,30V,1A,0,9W,150MHz	7c(9mm)	Tos	2SC2236,2SD863,2SD1207,2SD1331..
2SC2704	Si-NPN	AF-Pow,150/150V,0,05A,10W,200MHz	14h$	Tos	BF415,BF457..459,2SC3502,2SD1609,..
2SC2705	Si-NPN	=2SC2704:0,8W	7c(9mm)	Tos	BF297..299,BF422(A),2SC3467..69..
2SC2706	Si-NPN	AF/HF/Sw-Pow,140/140V,10A,100W,90MHz	18j$	Tos	2SC2837,2SC2987(A)
2SC2707	Si-NPN	AF,Sw-Pow,180/180V,15A,150W,80MHz	23a$	Tos	MJ15015,BDW16,2SC2607,2SD753..
2SC2708..2709	Si-NPN	-		Tos	-
2SC271	Si-NPN	UHF,25V,20mA,1100MHz	24b	Nec	BF362..363
2SC2710	Si-NPN	GenP,35V,0,8A,0,3W,120MHz	41c	Tos	BC337..338,BC635,BC637,2SD1225..
2SC2711	Si-NPN	VHF-Pow,35V,0,8A,Pq=6W(175MHz)	51r	Tos	-
2SC2712	Si-NPN	GenP,60V,0,15A,150MHz	35a	Tos	BC846,BCV71..72,2SC3323,2SC4076..
2SC2712-BL	Si-NPN	-	35	Tos	→2SC2712
2SC2712-GR	Si-NPN	-	35	Tos	→2SC2712
2SC2712-O	Si-NPN	-	35	Tos	→2SC2712

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2SC2712-Y	Si-NPN	-	35	Tos	→2SC2712
2SC2713	Si-NPN	GenP,LN,120V,0,1A,100MHz	35a	Toshiba	2SC3324,2SC3744,2SC4050
2SC2713-BL	Si-NPN	-	35	Tos	→2SC2713
2SC2713-GR	Si-NPN	-	35	Tos	→2SC2713
2SC2714	Si-NPN	HF,40V,0,02A,550MHz	35a	Toshiba	BF599,BF799,BFS20,2SC3015..
2SC2714-O	Si-NPN	-	35	Sanyo	→2SC2714
2SC2714-R	Si-NPN	-	35	Tos	→2SC2714
2SC2714-Y	Si-NPN	-	35	Tos	→2SC2714
2SC2715	Si-NPN	HF,35V,0,05A,>100MHz	35a	Toshiba	BF554,BFS18..19,BF840..841
2SC2715-O	Si-NPN	-	35	Tos	→2SC2715
2SC2715-R	Si-NPN	-	35	Tos	→2SC2715
2SC2715-Y	Si-NPN	-	35	Tos	→2SC2715
2SC2716	Si-NPN	HF/AF,35V,0,1A,120MHz	35a	Toshiba	BC846..848,BCW31..33,BF554..
2SC2716-O	Si-NPN	-	35	Tos	→2SC2716
2SC2716-R	Si-NPN	-	35	Tos	→2SC2716
2SC2717	Si-NPN	TV-IF-Out,30V,0,05A,>300MHz	7f	Tos	BF198..199,BF224..225,BFS96..597,..
2SC2718	Si-NPN	GenP,60V,0,1A,0,25W,250MHz	7c	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC2719	Si-NPN	HF/Sw,80V,0,3A,0,6W,50/560nS	7c	Nec	BC639,BSW63..64,2N2221A..2222A..
2SC272	Si-NPN	UHF,25V,20mA,1200MHz	24b	Nec	BF362..363
2SC2720	Si-NPN	AF,Sw,60V,0,5A,0,6W,<35/275nS	7e	Nec	BSV59,BSW62,BSX49,2N2222(A)..
2SC2721	Si-NPN	GenP,60V,0,7A,1W,110MHz	9b	NEC	BC637,BC639,2N2221..22(A),2SD1226..
2SC2722	Si-NPN	AF,Sw-Pow,100/80V,15A,150W,20MHz	20j$	Sak	2SC2525..2526,2SC2564..2565,2SC2838,..
2SC2723	Si-NPN	Sw,Pow,450/400V,15A,150W,30MHz	18j$	Sak	BUP23,2SC3520,2SC4139,2SC4434..
2SC2724	Si-NPN	FM-IF,30V,30mA,200MHz	41c	Mit	BF240..241,BF254..255,BF594..595,..
2SC2725	Si-NPN	Dual,100V,0,1A,0,4W,100MHz	7-SIP/bg2	Mit	-
2SC2726	Si-NPN	UHF,15V,0,02A,0,2W,1100MHz	25u	Hit	2SC2464,2SC2466,2SC2144,2SC2360..
2SC2727	Si-NPN	VHF,TV-Tuner,15V,0,02A,>700MHz	25za	Hit	2SC2454,2SC2465
2SC2728	Si-NPN	UHF,15V,0,02A,0,2W,2500MHz	25u	Hit	2SC2466,2SC2353
2SC2729	Si-NPN	VHF,15V,0,05A,0,2W,1300MHz	25za	Hit	2SC2368,2SC2454,2SC2465
2SC273	Si-NPN	GenP,120V,0,05A,0,5W,150MHz	2a$	Nec	BF257..259,2SC3245(A),2SC3248..
2SC2730	Si-NPN	UHF-Osc,15V,0,05A,0,2W,1600MHz	24b	Hit	BF362..363
2SC2731	Si-NPN	UHF-Osc,20V,0,05A,0,2W,3500MHz	25u	Hit	BFQ59,BFQ70,2SC2143,2SC2844..
2SC2732	Si-NPN	UHF,30V,0,02A,1000MHz	35a	Hit	BFS17,2SC3005,2SC3016,2SC3161
2SC2733	Si-NPN	VHF,30V,0,05A,1000MHz	35a	Hit	BFS17,2SC3005,2SC3016,2SC3161
2SC2734	Si-NPN	UHF,20V,0,05A,3500MHz	35a	Hit	BFT75,2SC3014,2SC3773
2SC2735	Si-NPN	VHF/UHF-Osc,30V,0,05A,1200MHz	35a	Hit	BFS17,2SC3005,2SC3016,2SC3161
2SC2736	Si-NPN	VHF/UHF,30V,0,05A,2200MHz	35a	Hitachi	BFR53,BFT75,2SC3014,2SC3773
2SC2737	Si-NPN	UHF,LN,20V,0,08A,8GHz	7f	Nec	-
2SC2738	Si-NPN	Sw,Pow,500/400V,2A,25W,11MHz	17j$	Mat	BUX84..85,2SC2333,2SC2534,2SC3169,..
2SC2739	Si-NPN	Sw,Pow,500/400V,7A,40W,11MHz	17j$	Mat	BUT56(A),2SC2427,2SC3039,2SC3170..
2SC274..279	Si-NPN	-		Oki	-
2SC2740	Si-NPN	Sw,Pow,500/400V,10A,100W,11MHz	18j$	Mat	BUW12(A),2SC2789,2SC2828,2SC3042..
2SC2741	Si-NPN	VHF-Dr/Out,36V,1A,Pq=2,5W(175MHz)	-	Ful	-
2SC2742	Si-NPN	-		Fui	-
2SC2743	Si-NPN	VHF-Pow,36V,5A,Pq=15W(175MHz)	61s*	Fui	-
2SC2744	Si-NPN	UHF-Dr/Out,36V,1A,Pq=2,5W(470MHz)	-	Fui	-
2SC2745	Si-NPN	UHF-Pow,36V,4A,Pq=9W(470MHz)	61r*	Fui	-
2SC2746	Si-NPN	UHF-Pow,36V,5A,Pq=15W(470MHz)	61r*	Fui	-
2SC2747	Si-NPN	-		Fui	-
2SC2748	Si-NPN	Dual,30V,0,03A,0,4W,200MHz	5-SIP	Mit	-
2SC2749	Si-NPN	-	-		-
2SC2749(A)	Si-NPN	Sw,Pow,500V,10A,100W,<1/3,2µS	16j$	Nec	BUW12(A),2SC3042,2SC3435,2SC4138..
2SC2750	Si-NPN	Sw,Pow,150V,15A,100W,<1/1,8µS	16j$	Nec	2SC2944,2SC2987A,2SD1047,2SD1703..
2SC2751	Si-NPN	500V,15A,120W,50MHz	-		-
2SC2751(A)	Si-NPN	Sw,Pow,500V,15A,120W,<1/3,2µS	16j$	Nec	BUW13(A),2SC3435,2SC3520,2SC4140..
2SC2752	Si-NPN	Sw,Pow,500/400V,0,5A,10W,<1/3,5µS	14h$	Nec	BD410,BUX86..87,2SC2899,2SC3051
2SC2753	Si-NPN	UHF,17V,0,07A,0,3W,5GHz	7f	Tos	2SC2570(A),2SC3037
2SC2754	Si-NPN	Sw,35V,0,1A,0,1W,400MHz,30/470nS	7c	Tos	BSW41,BSY63,2N708,2N4123..24..
2SC2755	Si-NPN	VHF,30V,0,02A,600MHz	35a	Nec	BF599,BF799,BFS20,2SC3015..
2SC2756	Si-NPN	VHF-Mix,20V,0,02A,850MHz	35a	NEC	BF599,BF799,BFS20,2SC3015..
2SC2757	Si-NPN	VHF/UHF-M/ixOsc,30V,0,05A,1100MHz	35a	Nec	BFS17,2SC3005,2SC3016,2SC3161
2SC2757-T32	Si-NPN	-	35	Nec	→2SC2757
2SC2757-T33	Si-NPN	-	35	Nec	→2SC2757
2SC2757-T34	Si-NPN	-	35	Nec	→2SC2757

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2SC2758	Si-NPN	UHF-Pre,LN,30V,0,02A,1000MHz	35a	Nec	BFS17,2SC3077,2SC3161
2SC2758-U12	Si-NPN	-	35	Nec	→2SC2758
2SC2758-U13	Si-NPN	-	35	Nec	→2SC2758
2SC2758-U14	Si-NPN	-	35	Nec	→2SC2758
2SC2759	Si-NPN	VHF/UHF-Mix/Osc,30V,0,05A,2000MHz	35a	Nec	BFS17,2SC3005,2SC3016,2SC3161
2SC2759-U21	Si-NPN	-	35	Nec	→2SC2759
2SC2759-U22	Si-NPN	-	35	Nec	→2SC2759
2SC2759-U23	Si-NPN	-	35	Nec	→2SC2759
2SC2760	Si-NPN	UHF-Pow,50V,10A,Pq=34W(470MHz)	?57s*	Fui	2N6439,2SC2796,2SC2895
2SC2761	Si-NPN	Sw,Pow,450/400V,30A,200W	23a$	Sanken	BUS14(A),BUS98(A),2SC2930,2SC3058
2SC2761-Y	Si-NPN	-	35	Tos	→2SC2761
2SC2762	Si-NPN	UHF-Dr/Out,35V,0,4A,Pq=1,4W(500MHz)	2a$	Nec	BFS50,MRF629,2SC2852,2SC3185
2SC2763	Si-NPN	UHF-Pow,35V,4A,Pq=16W(500MHz)	58r*	Nec	2SC1968
2SC2764..2765	Si-NPN	-		Nec	-
2SC2766	Si-NPN	AF,Sw-Pow,160/160V,15A,150W,60MHz	20j$	Nec	2SC2526,2SC2565,2SC2921..2922..
2SC2766A	Si-NPN	=2SC2766:180/180V	20j$	-	2SC2773..2774,2SC2922,2SC3370..
2SC2767	Si-NPN	Sw,Pow,250/200V,5A,40W,<1/3µS	17j$	Fjd	BU406..409,MJE51T..53T,2SC3056..
2SC2768	Si-NPN	Sw,Pow,250/200V,7A,40W,<1/3µS	17j$	Fjd	BU406..409,TIP150..152,2SC4106..
2SC2768A	Si-NPN	=2SC2768:10A	17j$	-	BUV27(A),2SC2867
2SC2769	Si-NPN	Sw,Pow,250/200V,10A,100W,<0,8/2,5µS	18j$	Fjd	TIP160..162,2SC2537,2SC2944,2SC2961..
2SC2770	Si-NPN	Sw,Pow,600V,100A,770W,<4/11µS	-	Fjd	-
2SC2771	Si-NPN	Dual,60V,0,1A,0,5W,140MHz	7-SIP/bp4	Mit	-
2SC2772	Si-NPN	-		Mit	-
2SC2773	Si-NPN	Sw,Pow,200/200V,15A,150W,20MHz	20j$	Sak	2SC3370,2SC3264,2SC3857,2SD846
2SC2774	Si-NPN	Sw,Pow,200/200V,17A,200W,20MHz	20j$	Sak	2SC3264
2SC2775	Si-NPN	GenP,90V,0,05A,200MHz	35a	Hitachi	2SC1622A,2SC3324,2SC4050
2SC2776	Si-NPN	FM/VHF,30V,0,03,320MHz	35a	Hit	BFS99,BF799,BFS20,2SC3015..
2SC2776-A	Si-NPN	-	35	Hit	→2SC2776
2SC2776-B	Si-NPN	-	35	Hit	→2SC2776
2SC2776-C	Si-NPN	-	35	Hit	→2SC2776
2SC2777	Si-NPN	-		Tos	-
2SC2778	Si-NPN	AM/FM,30V,0,03A,230MHz	35a	Matsushita	BF554,BF599,BF799,BFS18..20..
2SC2778-B	Si-NPN	-	35	Mat	→2SC2778
2SC2778-C	Si-NPN	-	35	Mat	→2SC2778
2SC2779	Si-NPN	-		Nec	-
2SC2780	Si-NPN	GenP,140V,0,05A,120MHz	39b	Nec	2SC2880,2SD1009,2SD1464
2SC2780-NK	Si-NPN	-	39	Nec	→2SC2780
2SC2780-NL	Si-NPN	-	39	Nec	→2SC2780
2SC2780-NM	Si-NPN	-	39	Nec	→2SC2780
2SC2781	Si-NPN	UHF-Osc/Dr/Out,35V,0,5A,Pq=0,9W(2,3GHz)	62c$	Fui	-
2SC2782	Si-NPN	VHF-Pow,36V,20A,Pq=90W(175MHz)	57r	Tos	-
2SC2783	Si-NPN	UHF-Pow,36V,8A,Pq=45W(470MHz)	57r	Tos	BLV45/12
2SC2784	Si-NPN	GenP,LN,120V,0,05A,0,3W,110MHz	40c	Nec	2SC1775(A),2SC2240,2SC2459,2SC3378,..
2SC2785	Si-NPN	GenP,60V,0,1A,0,25W,250MHz	40c	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC2786	Si-NPN	FM,30V,20mA,600MHz	40c	Nec	BF225,BF314,BF502,BF505,BF507..
2SC2787	Si-NPN	AM,50V,30mA,250MHz	40c	Nec	BF240..241,BF254..255,BF594..595,..
2SC2788	Si-NPN	Sw,Pow,500/400V,8A,80W,20MHz	18j$	Shi	BUP22,TIP58A,2SC2536,2SC3040..
2SC2789	Si-NPN	Sw,Pow,500/400V,10A,100W	18j$	Shi	BUP23,2SC2828,2SC3042,2SC4138..
2SC2790(A)	Si-NPN	Sw,Pow,850/800V,2A,80W,<1/5µS	23a$	Tos	BU326A,BU426A,BUW11(A),BUX46(A)..
2SC2791	Si-NPN	Sw,Pow,900V,5A,100W,<1/4,5µS	23a$	Tos	BU426A,BUS11A,BUW11A,2SC3796A..
2SC2792	Si-NPN	Sw,Pow,850/800V,2A,80W,<1/5µS	18j$	Tos	BU426A,BUW11(A),2SC3151..3152..
2SC2793	Si-NPN	Sw,Pow,900/800V,5A,100W,<1/4,5µS	20j$	Tos	2SC2980
2SC2794	Si-NPN	AF,Sw-Pow,60V,2A,25W,40MHz	14h$	Tos	BD177,BD235,BD377,2SD794(A)..
2SC2796	Si-NPN	UHF-Pow,45V,6A,Pq=44W(470MHz)	57s*	Mit	2N6439,2SC2895
2SC2797	Si-NPN	UHF-Pow,45V,1A,Pq=6W(770MHz)	?55s*	Mit	-
2SC2798	Si-NPN	UHF-Pow,45V,2A,Pq=14W(770MHz)	?55s*	Mit	-
2SC2799	Si-NPN	UHF-Pow,45V,4A,Pq=27W(770MHz)	?55s*	Mit	-
2SC28	Si-NPN	GenP,40V,0,05A,0,225W,100MHz	2a	Fui	BC167,BC182,BC237,BC547,2N2218..
2SC280(H)	Si-NPN	Dual,30V,0,01A,0,08W	-	Hit	-
2SC2800	Si-NPN	UHF-Pow,45V,6A,Pq=42W(770MHz)	57s*	Mit	-
2SC2801	Si-NPN	-		Mit	-
2SC2802	Si-NPN	AF/Mid-Out,300V,0,2A,10W,80MHz	30j$	Nec	(BF417,BF617,BF758..759,MPSU10..)
2SC2803	Si-NPN	AF/HF/Sw-Pow,150/150V,1A,20W,200MHz	14h$	Mat	2SC2690A,2SC3117,2SD669,2SD1563A
2SC2804	Si-NPN	UHF,25V,0,02A,0,2W,900MHz	25u	Tos	2SC2464,2SC2466,2SC2144,2SC2360..

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2SC2805	Si-NPN	UHF,30V,0,05A,0,2W,1500MHz	25zh	Tos	2SC2464,2SC2466,2SC2144,2SC2360..
2SC2806	Si-NPN	VHF,30V,0,05A,0,2W,1100MHz	25zh	Tos	2SC2464,2SC2466,2SC2144,2SC2360..
2SC2807	Si-NPN	-		Fui	-
2SC2808	Si-NPN	100V,50mA,0.5W,140MHz	-		-
2SC2808(S)	Si-NPN	GenP,160V,0,05A,0,5W,140MHz	7c,41c	Rhm	BF297..299,BF422,2SC3248,2SC3467,..
2SC2809	Si-NPN	Sw,Pow,300/300V,2A,50W,20MHz	18j$	Sak	TIP51..54,2SC2624
2SC281(H)	Si-NPN	GenP,30V,0,1A,0,2W,>80MHz	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC2810	Si-NPN	Sw,Pow,500/400V,7A,50W,18MHz	17j$	Sak	MJE13006,2SC3170,2SC4055,2SC4106..
2SC2811	Si-NPN	UHF-Dr/Out,45V,1A,Pq=1,4W(950MHz)	-	Nec	-
2SC2812	Si-NPN	GenP,55V,0,15A,100MHz	35a	Sanyo	BC846..847,BCW71..72,2SC3323..
2SC2812-L4	Si-NPN	-	35	Sanyo	→2SC2812
2SC2812-L5	Si-NPN	-	35	Sanyo	→2SC2812
2SC2812-L6	Si-NPN	-	35	Sanyo	→2SC2812
2SC2812-L7	Si-NPN	-	35	Sanyo	→2SC2812
2SC2813	Si-NPN	VHF,25V,0,03A,600MHz	35a	Sanyo	BF599,BF799,BFS20,2SC3015..
2SC2813-Q2	Si-NPN	-	35	Sanyo	→2SC2813
2SC2813-Q3	Si-NPN	-	35	Sanyo	→2SC2813
2SC2813-Q4	Si-NPN	-	35	Sanyo	→2SC2813
2SC2813-Q5	Si-NPN	-	35	Sanyo	→2SC2813
2SC2814	Si-NPN	HF,30V,0,03A,320MHz	35a	Sanyo	BFS54,BFS18..20,BF599,BF799..
2SC2814-F2	Si-NPN	-	35	Sanyo	→2SC2814
2SC2814-F3	Si-NPN	-	35	Sanyo	→2SC2814
2SC2814-F4	Si-NPN	-	35	Sanyo	→2SC2814
2SC2814-F5	Si-NPN	-	35	Sanyo	→2SC2814
2SC2815	Si-NPN	Sw,Pow,300/250V,5A,40W,<0,5/2µS	17j$	Hit	BU406..408,MJE51T..53T,2SC2907..
2SC2816	Si-NPN	Sw,Pow,500/400V,5A,40W,<0,5/2µS	17j$	Hit	BUT52,BUT56(A),2SC4106,2SC3497..
2SC2817	Si-NPN	Sw,Pow,300/250V,10A,80W,<0,5/2µS	20j$	Hit	2SC2650
2SC2818(H)	Si-NPN	Sw,Pow,500/400V,10A,100W,<0,5/2µS	23a$	Hitachi	BUW25,BUW34..35,2SC3046,2SC4138..
2SC2819(H)	Si-NPN	Sw,Pow,500/400V,15A,100W,<0,5/2µS	23a$	Hitachi	BUV25,BUW44,BUX25,2SD641..
2SC282(H)	Si-NPN	=2SC281:0,35W	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC2820	Si-NPN	Sw,Pow,500/400V,20A,125W,<1/3,5µS	23a$	Hitachi	2SC3085,2SC3094,2SC3593,2SC4110
2SC2821	Si-NPN	GenP,20V,0,05A,230MHz	3Sa	Hitachi	BC846..848,BCW31..33,BCW71..72..
2SC2821-D	Si-NPN	-	35	Hit	→2SC2821
2SC2821-E	Si-NPN	-	35	Hit	→2SC2821
2SC2821-F	Si-NPN	-	35	Hit	→2SC2821
2SC2822	Si-NPN	Sw,75V,0,8A,0,36W,<35/300nS	2a$	Nec	BSW63..64,2N2221A..2222A,2SC3733
2SC2823	Si-NPN-Darl	AF,Sw-Pow,120/120V,7A,70W,B=15000	16j$	Tos	BDV65C,2SD1123,2SD1210
2SC2824	Si-NPN	AF-Dr-Pow,120/120V,1A,15W,120MHz	14h$	Tos	2SC2690(A),2SC3117,2SD669,2SD1563
2SC2825	Si-NPN	Hi-beta,80V,6A,70W,B>500	18j$	Sak	2SD1831
2SC2826	Si-NPN	Sw,Pow,500/400V,3A,40W,20MHz	17j$	Shi	BUT93,TIP75C,2SC3038,2SC4105..
2SC2827	Si-NPN	Sw,Pow,500/400V,6A,50W,20MHz	17j$	Shi	MJE13006,2SC3830,2SC4106..
2SC2828	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/2,5µS	18j$	Shi	BUP23,2SC2789,2SC3042,2SC4138..
2SC2829	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/2,5µS	23a$	Shidengen	BUW25..26,BUW34..36,2SC3046,2SC4138
2SC283(H)	Si-NPN	=2SC281:50V,0,35W	2a	Hit	BC167,BC182,BC237,BC547,2SD767..
2SC2830	Si-NPN	Sw,Pow,500/400V,20A,200W,<1/2,5µS	23a$	Shidengen	2SC3085,2SC3094,2SC3593,2SC4110
2SC2831	Si-NPN	Sw,Pow,800/500V,1,5A,25W	17j$	Mat	BUV36(A),BUX84..85,2SC3149,2SC3352
2SC2831A	Si-NPN	=2SC2831:900/500V	17j$	-	BUV36A,BUX85,2SC3149,2SC3531..
2SC2832	Si-NPN	Sw,Pow,800/500V,5A,40W	17j$	Mat	BUT11(A),BUV46(A),2SC3047,2SC3050..
2SC2832A	Si-NPN	=2SC2832:900/500V	17j$	-	BUT11A,BUV46A,2SC3050
2SC2833	Si-NPN	Sw,Pow,800/500V,5A,100W	18j$	Mat	BUW11(A),BUW131(A),2SC3153,2SC3232+
2SC2833A	Si-NPN	=2SC2833:900/500V	18j$	-	BUW11A,BUW131A,2SC3153,2SC3232..
2SC2834	Si-NPN	Sw,Pow,800/500V,7A,100W	18j$	Mat	BUV47(A),BUW12(A),2SC3450,2SC3797..
2SC2834A	Si-NPN	=2SC2834:900/500V	18j$	-	BUV47A,BUW12A,2SC3536,2SC3636..
2SC2835..2836	Si-NPN	-		Nec	-
2SC2837	Si-NPN	AF,Sw-Pow,150/150V,10A,100W,70MHz	18j$	Sak	2SC2987A,2SC3907,2SD1047,2SD1703..
2SC2838	Si-NPN	=2SC2837:12A,120W	20j$	Sak	2SC2526,2SC2565,2SC2766,2SC2921..
2SC2839	Si-NPN	FM/VHF,30V,30mA,320MHz	40c	Sanyo	BF225,BF314,BF502,BF505,BF959..
2SC284(H)	Si-NPN	=2SC281:70V,0,35W	2a	Hit	BC174,BC182,BC190,BC546,2SC1890+
2SC2840	Si-NPN	VHF,25V,30mA,600MHz	40c	Sanyo	BF225,BF314,BF502,BF505,BF507..
2SC2841	Si-NPN	Sw,Pow,500/400V,7A,70W,<1/4µS	18j$	Mat	BUP22,TIP58A,2SC2788,2SC3040..
2SC2843	Si-NPN	UHF-Tuner	-	Mat	-
2SC2844	Si-NPN	UHF,25V,0,07A,4,5GHz	25u	Mat	BFP96,BFQ73,2SC3302
2SC2845	Si-NPN	UHF,LN,25V,0,07A,4,5GHz	35a	Mat	2SC3161,2SC3774..75
2SC2847	Si-NPN	VHF,AGC,30V,0,02A,>600MHz	35a	Mat	BF799,2SC3015,2SC3374

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2SC285	Si-NPN	VHF-A/Dr,50V,0,2A,0,5W,320MHz	2a$	Fui	BFW16..17,BFX55,2SC2852
2SC2850	Si-NPN	UHF-Pow,35V,3A,Pq=11W(860MHz)	58r*	Nec	2SC2559
2SC2851	Si-NPN	VHF-Osc/Dr,36V,0,3A,Pq=0,9W(175MHz)	7c(9mm)	Mat	2SC2053
2SC2852	Si-NPN	UHF-Osc/Dr,36V,0,5A,Pq=1W(470MHz)	2a$	Mat	BFS50,MRF629,2N3948,2SC2762..
2SC2853	Si-NPN	GenP,90V,0,1A,0,4W,310MHz	7c	Hit	2SC1775(A),2SC2240,2SC2459,2SC3245,..
2SC2854	Si-NPN	=2SC2853:120/120V	7c	Hit	2SC1775(A),2SC2240,2SC2459,2SC3245,..
2SC2855	Si-NPN	=2SC2853:ra	7c	Hit	2SC1775(A),2SC2240,2SC2389,2SC2459,..
2SC2856	Si-NPN	=2SC2853:ra,120V	7c	Hit	2SC1775A,2SC2240,2SC2389,2SC2459,..
2SC2857	Si-NPN	AF/VD-Driver,180V,0,05A,0,5W,>50MHz	7c	Sanyo	BF298..299,BF422,2SC3467..68..
2SC2858	Si-NPN	Sw,Pow,500/400V,8A,65W,<1/3,5µS	20j$	Hit	2SC2650,2SC2818
2SC2859	Si-NPN	GenP,35V,0,5A,300MHz	35a	Toshiba	BC817..818,BCX19..20,2SC3341..
2SC2859-0	Si-NPN	-	35	Tos	→2SC2859
2SC2859-Y	Si-NPN	-	35	Tos	→2SC2859
2SC285A	Si-NPN	=2SC285:0,3A,500MHz	2a$	-	BFX55,2SC2852
2SC286	Si-NPN	FM/VHF,20V,10mA,>600MHz	24b	Nec	BF362..363
2SC2860	Si-NPN	FM/VHF,30V,15mA,650MHz	40c	Mat	BF225,BF314,BF502,BF505,BF507..
2SC2861..2864	Si-NPN	-		Son	-
2SC2865(A)	Si-NPN	Sw,Pow,250V,20A,200W,<0,9/1,9µS	23a$	Shidengen	BUV11..12,BUX11..12,BUW58,BUW73
2SC2866	Si-NPN	-		Mat	-
2SC2867	Si-NPN	Sw,Pow,300/200V,10A,50W,<1/1,5µS	17j$	Hit	BUS37,BUV27A..28,3SC3057,2SC3562
2SC2868	Si-NPN	GenP,80V,0,1A,0,4W,200MHz	7c	Tos	BC546,2SC2240,2SC2459,2SC3245(A)..
2SC2869	Si-NPN	UHF,LN,20V,0,08A,0,4W,8GHz	25za	Nec	2SC2368,2SC2876
2SC287(A)	Si-NPN	FM/VHF,20(A=35)V,10mA,>600MHz	24b	Nec	BF362..363
2SC2870(L)	Si-NPN	AF/Vid-Out,300/300V,0,1A,10W,80MHz	30j$	Hit	2SC2924,2SC3408,2SC3805,2SC4019..
2SC2871(L,S)	Si-NPN-Darl	AF,Sw-Pow,60V,1A,8W,B>2000,<0,2/5µS	30j$	Hit	2SC4500,2SD1574,2SD1598,2SD1800..
2SC2872(S)	Si-NPN	GenP,50V,0,7A,0,3..0,4W,120MHz	7c,40c	Rhm	BC337,BC637,BC639,2SD667,2SD1226+
2SC2873	Si-NPN	GenP,50V,2A,100MHz,0,1/1,1µS	39b	Tos	2SD1422,2SD1623
2SC2873-0	Si-NPN	-	39	Tos	→2SC2873
2SC2873-Y	Si-NPN	-	39	Tos	→2SC2873
2SC2874	Si-NPN	-		Mat	-
2SC2875	Si-NPN	HF/Sw,35V,0,1A,0,2W,400MHz	41c	Tos	BSW41,BSY63,2N708,2N4123..24..
2SC2876	Si-NPN	UHF,LN,15V,0,08A,0,2W,7GHz	25q	Tos	2SC2876,2SC3358,2SC3603
2SC2877	Si-NPN	AF-Pow,40V,3A,10W,100MHz	14h$	Tos	BD785,2SD1348,2SD1506,2SD1818..
2SC2878	Si-NPN	Hi-Ueb,Sw,50V,0,3A,0,4W,30MHz	7c	Tos	2SC3615,2SC3836,2SD1915
2SC2879	Si-NPN	AM-Pow,45V,25A,Pep=100W(28MHz)	59r	Tos	-
2SC288(A)	Si-NPN	UHF-Osc,30(A=35)V,20mA,>850MHz	24b	Nec	BF362..363
2SC2880	Si-NPN	Vid,200V,0,05A,120MHz	39b	Tos	BF620,BF622,BFN20,2SC3380..
2SC2880-0	Si-NPN	-	39	Tos	→2SC2880
2SC2880-Y	Si-NPN	-	39	Tos	→2SC2880
2SC2881	Si-NPN	GenP,120V,0,8A,120MHz	39b	Tos	2SD1007,2SD1418..1419
2SC2881-0	Si-NPN	-	39	Tos	→2SC2881
2SC2881-Y	Si-NPN	-	39	Tos	→2SC2881
2SC2882	Si-NPN	GenP,80V,0,4A,100MHz	39b	Tos	2SC3438,2SD875,2SD968(A)
2SC2882-0	Si-NPN	-	39	Tos	→2SC2882
2SC2882-Y	Si-NPN	-	39	Tos	→2SC2882
2SC2883	Si-NPN	GenP,30V,1,5A,120MHz	39b	Tos	2SC2873,2SC2982,2SD1621
2SC2884	Si-NPN	GenP,35V,0,8A,120MHz	39b	Tos	BCX54..56,2SC3444,2SC4376,2SD1662,..
2SC2884-0	Si-NPN	-	39	Tos	→2SC2884
2SC2884-Y	Si-NPN	-	39	Tos	→2SC2884
2SC2885	Si-NPN	Sw,Pow,330V,2A,15W,<1/3µS	30j$	Nec	2SC2946,2SC3233,2SC3631,2SC4616
2SC2886	Si-NPN	VHF-Pow,55V,0,75A,Pq=5W(175MHz)	55s	Nec	BLY91,BLY97
2SC2887	Si-NPN	VHF-Pow,55V,1,5A,Pq=14W(175MHz)	55s	Nec	BLY92
2SC2888	Si-NPN	VHF-Pow,55V,3A,Pq=28W(175MHz)	55s	Nec	-
2SC2889	Si-NPN	VHF-Pow,55V,6A,Pq=40W(175MHz)	55s	Nec	BLW25,2N5643,2SC2182
2SC288A	Si-NPN	35V,20mA,0.15W	-		-
2SC289	Si-NPN	UHF-Pre-in/Mix,25V,10mA,>900MHz	24b	Nec	BF362..363
2SC2890	Si-NPN	VHF-Pow,55V,12A,Pq=84W(175MHz)	57s	Nec	MRF317
2SC2891	Si-NPN	VHF-Pow,55V,15A,Pq=112W(175MHz)	57s	Nec	2SC2609
2SC2892	Si-NPN	UHF-Pow,55V,0,75A,Pq=4W(400MHz)	55s	Nec	BLW90,BLY37
2SC2893	Si-NPN	UHF-Pow,55V,1,5A,Pq=10,7W(400MHz)	55s	Nec	BLW91
2SC2894	Si-NPN	UHF-Pow,55V,3A,Pq=22,4W(400MHz)	55s	Nec	BLX95,2N6105
2SC2895	Si-NPN	UHF-Pow,55V,6A,Pq=40W(400MHz)	57s	Nec	2SC2796
2SC2896	Si-NPN	UHF-Pow,55V,12A,Pq=63W(400MHz)	57s	Nec	2SC2186
2SC2897	Si-NPN	UHF-Pow,55V,15A,Pq=100W(400MHz)	57s	Nec	-

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2SC2898	Si-NPN	Sw,Pow,500/400V,8A,50W	17j$	Hit	MJE13006,2SC3039,2SC3170,2SC4106..
2SC2899	Si-NPN	Sw,Pow,500/400V,0,5A,10W,<1/3µS	14h$	Hit	BD410,BUX86..87,2SC2752,2SC3051
2SC29	Si-NPN	=2SC28:0,025A,0,115W	2a	Fui	BC167,BC182,BC237,BC547,2N2218..
2SC290	Si-NPN	FM/VHF-Pow,70V,2A,Pq=6W(100MHz)	2a$	Nec	-
2SC2900	Si-NPN	Sw,Pow,350/300V,4A,90W,10MHz	18j$	Sak	TIP51..54,2SC2624,2SC3083
2SC2901	Si-NPN	Fast-Sw,40V,0,2A,0,6W,<12/18nS	7e	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC2902	Si-NPN	Sw,Pow,800/400V,15A,150W,<1,5/4,5µS	23a$	Org	BUS13(A),BUW45..46,BUX48(A..C)..
2SC2903	Si-NPN	Sw,Pow,800/400V,25A,200W,<1,5/4,5µS	23a$	Org	BUS14(A),BUS98(A),2SC3094,2SC3593
2SC2904	Si-NPN	AM-Pow,50V,22A,Pq=110W(30MHz)	57s*	Mit	-
2SC2905	Si-NPN	UHF-Pow,35V,15A,Pq=50W(520MHz)	57s*	Mit	2SC3102
2SC2906	Si-NPN	UHF-Pow,25V,2,2A,Pq=6,3W(500MHz)	58r*	Nec	-
2SC2906A	Si-NPN	=2SC2906:3A,Pq=7W(500MHz)	58r*	-	-
2SC2907	Si-NPN	Sw,Pow,400/350V,5A,40W,<2/5,5µS	17j$	Fjd	BU406,BU408,MJE52T..53T,2SC3056,..
2SC2908	Si-NPN	Sw,Pow,200/100V,5A,50W,<0,5/3µS	16j$	Nec	2SC2908,2SC3263,2SC4799
2SC2909	SI-NPN	GenP,180V,0,07A,0,6W,150MHz	7c	Sanyo	BF298..299,BF422A,2SC3248,2SC3467..
2SC291	SI-NPN	AF,Sw,70V,3A,1W,90MHz	2a$	Son	2N4238..4239,2SC2214
2SC2910	Si-NPN	GenP,180V,0,07A,0,9W,150MHz	7c(9mm)	Sanyo	BF422A,2SC3248..49,2SC3467..68
2SC2911	Si-NPN	GenP,Pow,180V,0,14A,10W,150MHz	14h$	Sanyo	BF415,2SC3601,2SC4704
2SC2912	Si-NPN	=2SC2911:200V	14h$	Sanyo	BF415,2SC3601,2SC4704
2SC2913	Si-NPN	Sw,Pow,500/400V,7A,40W,<1/3,5µS	22a$	Tos	MJE13006,2SC2739,2SC3039,2SC4106..
2SC2914	Si-NPN	Sw,Pow,500/400V,10A,120W,<1/3,5µS	23a$	Toshiba	BUW25..26,BUW34..36,2SC3043..
2SC2915	Si-NPN	UHF-Pow,35V,20A,175W,Pq=66W(500MHz)	57s	Nec	-
2SC2917	Si-NPN	VHF-Pow,35V,20A,175W,Pq=83W(175MHz)	57s	Nec	-
2SC2918	Si-NPN	UHF-Pow,35V,5A,Pq=21W(860MHz)	58r*	Nec	-
2SC2919	Si-NPN	-		Nec	-
2SC292(S)	Si-NPN	=2SC291:100V	2a$	Son	2N4239,2SC2214
2SC2920	Si-NPN	Sw,Pow,Reg-Pow,450V,15A,150W,30MHz	23a$	Fujitsu	BUV25,BUW44,BUX25,2SD641..
2SC2921	Si-NPN	AF,Sw-Pow,160/160V,15A,150W,60MHz	20j$	Sak	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SC2922	Si-NPN	AF,Sw-Pow,180/180V,17A,200W,50MHz	20j$	Sak	2SC2774,2SC3264,2SC3858
2SC2923	Si-NPN	Vid-Pow,300/300V,0,1A,15W,140MHz	13j$	Matsushita	(BF617,BF758..759,BF859,..)
2SC2924	Si-NPN	=2SC2923:10W	30j$	Mat	2SC2870,2SC3408,2SC3805,2SC4019..
2SC2925	Si-NPN	Hi-beta,Hi-Ueb,60V,0,7A,0,75W,200MHz	7c	Mat	2SD1582,2SD1779
2SC2926(S)	Si-NPN	VHF-Mix/Osc,UHF-Osc,30V,50mA,1100MHz	7c,41c	Rhm	BF357,BF377..378,BF689K,BF763..
2SC2927	Si-NPN	Vid-Pow,300/300V,0,2A,10W,80MHz	?17j$	Hit	2SC1505..1507,2SC1755..1757,2SC1905
2SC2928	Si-NPN	CTV-HD,1500/800V,5A,50W	23a$	Hitachi	BU208A,BU508A,2SD792,2SD954..
2SC2929	Si-NPN	Sw,Pow,450/400V,3A,40W,<1,5/2,8µS	17j$	Fjd	BUT93,TIP75B,C,2SC2826,2SC3038..
2SC293(S)	Si-NPN	=2SC291:130V	2a$	Son	BUX49..50,BUY41
2SC2930	Si-NPN	Sw,Pow,500/400V,30A,200W,<1/4µS	23a$	Fujitsu	BUS14(A),BUS98(A),2SC3058
2SC2931	Si-NPN	UHF-Pow,35V,0,6A,Pq=1,7W(900MHz)	58s*	Mit	-
2SC2932	SI-NPN	UHF-Pow,35V,2A,Pq=7W(900MHz)	58s*	Mit	-
2SC2933	Si-NPN	UHF-Pow,35V,4A,Pq=16W(900MHz)	58s*	Mit	-
2SC2934	Si-NPN	AF/Vid-Pow,300/300V,0,2A,12,5W,80MHz	14h$	Hit	BF417,BF459,2SC2621,2SC3417..
2SC2935	Si-NPN	=2SC2934:15W	14h$	Hit	BF459
2SC2936	Si-NPN	Sw,Pow,500/400V,30A,150W,<1/4µS	23a$	Hitachi	BUS14(A),BUS98(A),2SC3058
2SC2937	Si-NPN	Sw,Pow,500/400V,8A,80W,<1/3,7µS	16j$	Shi	BUP22,TIP58A,2SC2788,2SC3040..
2SC2938	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/3,7µS	16j$	Shi	BUP23,2SC2789,2SC3042,2SC4138..
2SC2939	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/2,5µS	16j$	Shi	BUP23,2SC2789,2SC3042,2SC4138..
2SC294(-M)	Si-NPN	Dual,25V,0,05A,0,6W,200MHz	81bt	Nec	-
2SC2940	Si-NPN	Sw,Pow,230/230,30A,300W,<0,9/2µS	68a$	Shi	2SC1301,2SC2249,2SC2445,2SC3224..
2SC2941	Si-NPN	UHF-Osc,25V,0,22A,5,5W,6GHz	-	Nec	-
2SC2942	Si-NPN	Sw,Pow,230/230,50A,200W,<1,2/2µS	68a$	Sak	2SC1437
2SC2943	Si-NPN	Sw,Pow,390/250V,15A,80W,70MHz	18j$	Son	BUP23,2SC2626,2SC3520,2SC4139..
2SC2944	Si-NPN	Sw,Pow,250/200V,15A,100W,<0,8/1,9µS	18j$	Fjd	2SC2307,2SC2626,2SC3520,2SC4139..
2SC2946(1)	Si-NPN	Sw,Pow,330/200V,2A,15W,<1/3µS	30j$	Nec	2SC2885,2SC3233,2SC3631,(BUV93..95)
2SC2947	Si-NPN	GenP,60V,0,1A,0,25W,250MHz	40c	Nec	BC174,BC182,BC190,BC546,2SD767..
2SC2948	Si-NPN	Sw,Pow,500/400V,50A,300W,<1/4µS	?74	Hit	-
2SC2949	Si-NPN	UHF-Osc,25V,0,11A,2,75W,6,5GHz	-	Nec	-
2SC295	Si-NPN	Dual,15V,0,05A,0,6W,200MHz	81bu	Nec	-
2SC2950	Si-NPN	UHF-Osc,25V,0,22A,5,5W,6GHz	-	Nec	-
2SC2951	Si-NPN	UHF-Osc,25V,0,44A,9,7W,5,5GHz	62b$	Nec	-
2SC2952	Si-NPN	UHF,30V,0,25A,2,5GHz	5g	Nec	2SC1199,2SC1252,2SC1365..66
2SC2953	Si-NPN	UHF,30V,0,25A,5W	55s	Nec	BFR65,2SC1249..1251
2SC2954	Si-NPN	VHF,35V,0,15A,4000MHz	39b	Nec	BFQ18
2SC2955	Si-NPN	VHF,15V,5mA,0,05W,4GHz	51s	Nec	BFQ59..60,BFQ70..71,2SC2143

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2SC2956	Si-NPN	VHF-Pow, 45V, 0,6A, Pq=1,6W(2,3GHz)	55r	Nec	-
2SC2957	Si-NPN	VHF-Pow, 45V, 1,2A, Pq=2,8W(2,3GHz)	55r	Nec	-
2SC2958	Si-NPN	GenP, 160/140V, 0,5A, 1W, 60MHz	9b	NEC	2SC2383, 2SC3228, 2SC3332
2SC2959	Si-NPN	=2SC2958: 160/160V	9b	Nec	2SC2383, 2SC3228, 2SC3332
2SC296	Si-NPN	HF-Pre/Mix/Osc., 20V, 25mA, 0,2W, 180MHz	5g	Fui	BF240..241, BF254..255, BF594..595,..
2SC2960	Si-NPN	Sw, 60V, 0,15A, 0,25W, <190/700nS	40c	Sanyo	BSV59, BSX49, 2N3302, 2N3904..
2SC2961	Si-NPN	Sw, Pow, 400/300V, 10A, 80W, <0,4/1,9µS	18j$	Fjd	TIP162, 2SC2537, 2SC2625, 2SC4768..
2SC2962	Si-NPN	Sw, Pow, 700/600V, 5A, 80W, <0,5/3µS	18j$	Fjd	BU426(A), BUW11(A), 2SC3153, 2SC3796..
2SC2963	Si-NPN	Sw, Pow, 70V, 3A, 40W, <0,5/4,2µS	17j$	Shi	2SC3252, (BD241A, BD537, BD937,..)
2SC2964	Si-NPN	Sw, Pow, Reg-Pow, 600/400V, 15A, 150W, 28MHz	23a$	Fujitsu	BUS13(A), BUW45..46, BUX48(A..C)
2SC2965	Si-NPN	=2SC2964: 600/450V	23a$	-	BUS13(A), BUW45..46, BUX48(A..C)
2SC2966	Si-NPN	Sw, Pow, 225/225V, 40A, 200W, <1/2µS	68a$	Nec	2SC2403, 2SC2366, 2SC2973, 2SD702
2SC2967	Si-NPN	FM, 30V, 0,02, 600MHz	40c	Nec	BF225, BF310, BF314, BFS02, BF505..
2SC2968	Si-NPN	AM, 50V, 0,03V, 250MHz	40c	Nec	BF240..241, BF254..255, BF594..595,..
2SC2969	Si-NPN	UHF-Pow, 36V, 4A, Pq=15W(470MHz)	61s*	Fui	-
2SC297	Si-NPN	=2SC291: 10W	43a$	Son	(BD787, BD789, MJE240..242,..)
2SC2970	Si-NPN	Sw, Pow, 300/200V, 5A, 40W, <1,5/4,5µS	22a$	Org	BU406..408, MJE51T..53T, 2SC2907..
2SC2971	Si-NPN	Sw, Pow, 300/200V, 10A, 100W, <1,5/4,5µS	23a$	Org	BUW72, BUX17A..C, BUX43, BUY18..
2SC2972	Si-NPN	Sw, Pow, 300/200V, 15A, 150W, <1,5/4,5µS	23a$	Org	BUX13, BUY50, MJ15022, MJ15024..
2SC2973	Si-NPN	Sw, Pow, 300/200V, 40A, 200W, <1,5/4,5µS	68a$	Org	2SC2366, 2SC2403, 2SD642, 2SD702
2SC2974	Si-NPN	Sw, Pow, 300/200V, 70A, 300W, <1,5/4,5µS	?74	Org	-
2SC2975	Si-NPN	Sw, Pow, 800/400V, 5A, 40W, <1,5/4,5µS	22a$	Org	BUT11(A), BUV46(A), 2SC3047, 2SC3087..
2SC2976	Si-NPN	Sw, Pow, 800/400V, 10A, 100W, <1,5/4,5µS	23a$	Org	BUS12(A), BUW26, BUW35..36, BUX81,..
2SC2977	Si-NPN	Sw, Pow, 800/400V, 30A, 200W, <1,5/4,5µS	68a$	Org	2SC2204, 2SD295
2SC2978	Si-NPN	Sw, Pow, 800/400V, 50A, 200W, <1,5/4,5µS	?74	Org	-
2SC2979	Si-NPN	Sw, Pow, 900/800V, 3A, 40W, <1/4µS	17j$	Hit	BUT11A, BUT56A, BUV46A, 2SC3150..
2SC298	Si-NPN	=2SC292: 10W	43a$	Son	(BD791, MJE243..244,..)
2SC2980	Si-NPN	Sw, Pow, 900/800V, 5A, 80W, <1/4µS	20j$	Hit	-
2SC2981	Si-NPN	Sw, Pow, 900/800V, 8A, 100W, <1/4µS	23a$	Hit	BU526, BU536, BUV47A, BUW12A..
2SC2982	Si-NPN	Lo-sat, 30V, 2A, 150MHz	39b	Tos	2SD1621, 2SD1623
2SC2982-A	Si-NPN	-	39	Tos	→2SC2982
2SC2982-B	Si-NPN	-	39	Tos	→2SC2982
2SC2982-C	Si-NPN	-	39	Tos	→2SC2982
2SC2982-D	Si-NPN	-	39	Tos	→2SC2982
2SC2983	Si-NPN	AF, Sw-Pow, 160/160V, 1,5A, 15W, 100MHz	30j$	Tos	2SC4027, 2SD1033, 2SD1080..82, 2SD1918
2SC2984	Si-NPN	UHF-Pow, 45V, 6A, Pq=25W(890MHz)	62a&	Nec	-
2SC2985	Si-NPN	UHF-Pow, 45V, 2A, Pq=7,9W(890MHz)	55s	Nec	-
2SC2986	Si-NPN	HF, 40V, 0,05A, 0,3W, 350MHz	7c	Tos	BF370, BF920..921S, BF959
2SC2987	Si-NPN	AF-Pow, 140/140V, 12A, 120W, 50MHz	16j$	Nec	2SD1047
2SC2987A	Si-NPN	=2SC2987: 160/160V	16j$	-	2SD1047
2SC2988	Si-NPN	VHF-Pow, 36V, 0,5A, Pq=2,2W(175MHz)	14h$	Mat	-
2SC2989	Si-NPN	VHF-Pow, 36V, 1A, Pq=10,5W(175MHz)	17f*	Mat	-
2SC299	Si-NPN	=2SC293: 10W	43a$	Son	(BDX36..37)
2SC2990	Si-NPN	VHF-Out, Pq>2,5W(150MHz)	-	Mat	-
2SC2991	Si-NPN	UHF-Pow, 36V, 0,6A, Pq=2,3W(470MHz)	58s*	Mat	-
2SC2992	Si-NPN	UHF-Pow, 36V, 1,5A, Pq=11W(470MHz)	58s*	Mat	-
2SC2995	Si-NPN	=2SC2986: 0,2W	41c	Tos	→2SC2986
2SC2996	Si-NPN	=2SC2986: SMD	35a	Tos	BF599, BF799, BFS20, 2SC3015..
2SC2996-O	Si-NPN	-	35	Tos	→2SC2996
2SC2996-R	Si-NPN	-	35	Tos	→2SC2996
2SC2996-Y	Si-NPN	-	35	Tos	→2SC2996
2SC2997	Si-NPN	UHF, 20V, 0,08A, 0,35W, 8GHz	52s	Nec	2SC2876, 2SC3062, 2SC3358, 2SC3603
2SC2998	Si-NPN	=2SC2960: 0,5W	7c	Sanyo	→2SC2960
2SC2999	Si-NPN	VHF, 25V, 30mA, 750MHz	40c	Sanyo	BF225, BF314, BFS02, BF505, BF959..
2SC30	Si-NPN	VHF, 60V, 0,08A, 0,5W, 280MHz	2a$	Nec	BFW16..17, BFX55, 2N3725, 2SC1385..
2SC300	Si-NPN	HF/GenP, 25V, 0,1A, 0,26W, 400MHz	2a$	Mit	BSW41, BSY62..63, 2N706A, 2N708..
2SC3000	Si-NPN	=2SC2839: 0,2SW	7c	Sanyo	→2SC2839
2SC3001	Si-NPN	VHF-Pow, 20V, 3A, Pq=7W(175MHz)	58s*	Mit	2SC1729
2SC3004	Si-NPN-Darl	AF, Sw-Pow, 30V, 3A, 10W, B>2000	14h$	Hit	BD675, BD775, 2N6037..6039..
2SC3005	Si-NPN	UHF-Osc, 15V, 0,05A, 1600MHz	35a	Hit	BFS17, 2SC3005, 2SC3016
2SC3006	Si-NPN	UHF-Pow, 35V, 1A, Pq>3W(470MHz)	58s	Tos	2SC3020
2SC3007	Si-NPN	Lo-sat, 50V, 2A, 8W(Tc=25°), 100MHz	2a$	Tos	(BC440..441, BSS15..16, 2N5320..21,..)
2SC3008	Si-NPN	VHF-Pow, 35V, 10A, Pq=40W(175MHz)	58r*	Nec	-
2SC3009	Si-NPN	UHF-Pow, 25V, 1,5A, Pq=3,5W(860MHz)	58r*	Nec	-

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2SC301	Si-NPN	=2SC300	2a$	Mit	BSW41,BSY62..63,2N706A,2N708..
2SC3010	Si-NPN	UHF-Pow,25V,3A,Pq=5,5W(860MHz)	58r*	Nec	-
2SC3011	Si-NPN	UHF,20V,0,03A,6,5GHz	35a	Tos	BFR182,2SC3583,2SC3585
2SC3012	Si-NPN	AF,Sw-Pow,130V,10A,100W,60MHz	16j$	Nec	2SC2706,2SC2837,2SC2987(A)
2SC3013	Si-NPN	VHF-Osc,15V,0,05A,900MHz	35a	Hit	BF599,BF799,BFS20,2SC3015
2SC3014	Si-NPN	UHF-Pre,15V,0,05A,3,4GHz	35a	Hitachi	BFT75,2SC3773
2SC3015	Si-NPN	VHF,15V,0,05A,1100MHz	35a	Hit	BF599,BF799,BFS20,2SC3130
2SC3016	Si-NPN	VHF/UHF-Osc,10V,0,05A,1450MHz	35a	Hit	BFS17,2SC3005,2SC3077
2SC3017	Si-NPN	VHF-Dr/Out,20V,0,6A,Pq=1,7W(175MHz)	2a*	Mit	-
2SC3018	Si-NPN	VHF-Pow,20V,1,5A,Pq=3,5W(175MHz)	58s*	Mit	-
2SC3019	Si-NPN	UHF-A/Dr,35V,0,4A,Pq=0,6W(520MHz)	25za	Mit	BLW12
2SC302	Si-NPN	=2SC300:50V	2a$	Mit	BSV59,BSX48..49,2N3903..3904..
2SC3020	Si-NPN	UHF-Pow,35V,1A,Pq=3,3W(520MHz)	58s*	Mit	2SC3006
2SC3021	Si-NPN	UHF-Pow,35V,2A,Pq=8W(520MHz)	58s*	Mit	2SC1967
2SC3022	Si-NPN	UHF-Pow,35V,7A,Pq=22W(520MHz)	58s*	Mit	2SC2695
2SC3023	Si-NPN	TV-HD,1500V,3A,50W,<2/5,5µS	23a$	Hitachi	BU208..209A,BU705,2SD850,2SD1494..
2SC3024	Si-NPN	=2SC3023:1700/800V	23a$	Hit	BU209A,2SD784..785,2SD1434
2SC3025	Si-NPN	TV-HD,1500/800V,6A,50W,<1,5/5,5µS	23a$	Hitachi	BU208A,BU508A,2SD649,2SD821..
2SC3026	Si-NPN	=2SC3025:1700/800V	23a$	Hit	2SC3028
2SC3027	Si-NPN	TV-HD,1500/800V,8A,50W,<2/5,5µS	23a$	Hitachi	BU508A,BU908,BU2508A,2SC4801
2SC3028	Si-NPN	=2SC3027:1700/800V	23a$	Hit	-
2SC3029	Si-NPN	UHF,15V,5mA,0,05W,4GHz	25za	Nec	BFG90..91,BFQ85
2SC303	Si-NPN	HF/GenP,50V,0,5A,0,8W,200MHz	2a$	Mit	BC140..141,BC300..302,2N3053..
2SC3030	Si-NPN-Darl	Sw,Pow,900/800V,7A,80W,B=15	18j$	Fjd	-
2SC3031	Si-NPN-Darl	=2SC3030:	23a$	Fjd	BUT16
2SC3032	Si-NPN-Darl	=2SC3030:900/700V	18j$	Fjd	-
2SC3033	Si-NPN-Darl	=2SC3030:900/700V	23a$	Fjd	BUT16
2SC3034	Si-NPN	Sw,Pow,250/200V,10A,100W,<1/3µS	23a$	Org	BUX17(A..C),BUX42..43,BUY18..
2SC3035	Si-NPN	Sw,Pow,300/200V,5A,40W,<1,5/4,5µS	22a$	Org	BU406..408,2N6234..35,2SC2907..
2SC3036	Si-NPN	=2SC3035:800/400V	22a$	Org	BUT11(A),BUV46(A),2SC3047,2SC3087..
2SC3037	Si-NPN	UHF,20V,0,07A,0,4W,5GHz	7f	Son	2SC2570(A),2SC3337,2SC3606
2SC3038	Si-NPN	Sw,Pow,500/400V,4A,40W,<1/3,5µS	17j$	Sanyo	BUT93,2SC2535,2SC2827,2SC4105..
2SC3039	Si-NPN	Sw,Pow,500/400V,7A,50W,<1/3,5µS	17j$	Sanyo	MJE13006,2SC2739,2SC3170,2SC4106..
2SC304	Si-NPN	HF/GenP,60V,0,5A,0,8W,220MHz	2a$	Mit	BC140..141,BC300..302,2N3053..
2SC3040	Si-NPN	Sw,Pow,500/400V,8A,80W,<1/3,5µS	18j$	Sanyo	BUP22,TIP58A,2SC2536,2SC2788..
2SC3041	Si-NPN	=2SC3040:	23a$	Sanyo	BUW25,BUW34,2SC2536,2SC2788..
2SC3042	Si-NPN	Sw,Pow,500/400V,12A,100W,<1/3,5µS	18j$	Sanyo	BUP23,2SC3520,2SC4139,2SC4434..
2SC3043	Si-NPN	=2SC3042:120W	23a$	Sanyo	BUW75..77,2SC3411,2SC3451,2SD641..
2SC3044	Si-NPN	Sw,Pow,Reg-Pow,450/400V,6A,100W,30MHz	23a$	Fujitsu	BUP22,BUX44,2SC2656,2SD640..
2SC3044A	Si-NPN	=2SC3044:450/450V	23a$	-	BUP22,BUX44,2SC2656,2SD640..
2SC3045	Si-NPN	Sw,Pow,Reg-Pow,450/400V,10A,100W,32MHz	23a$	Fujitsu	BUW24..26,BUW34..36,2SC3520,2SC4138..
2SC3046	Si-NPN	Sw,Pow,Reg-Pow,600/450V,10A,100W,28MHz	23a$	Fujitsu	BUW25..26,BUW35..36,2SC3451..
2SC3047	Si-NPN	Sw,Pow,850/500V,6A,40W,<1/4µS	17j$	Fjd	BUT11(A),BUT56(A),BUV46(A)..
2SC3048	Si-NPN	=2SC3047:50W	23a$	Fjd	BU426A,BU526,BUX47(A),2SD811..
2SC3049	Si-NPN	=2SC3047:10A,50W	23a$	Fjd	BU626A,BUS12(A),BUW36,2SD1094..
2SC305	Si-NPN	HF/GenP,80V,0,5A,0,8W,220MHz	2a$	Mit	BC140..141,BC300..301,2N1990..
2SC3050	Si-NPN	Sw,Pow,1200/800V,5A,150W,-/<4,5µS	23a$	Fui	BU546,BU903,2SC3214,2SC3343..
2SC3051	Si-NPN	Sw,Pow,500/400V,0,8A,10W,-/4µS	14h$	Tos	BD410,2SC3840
2SC3052-E	Si-NPN	50V,0.2A,0.15W,200MHz	35a	Mit	BC846..847,BCW71..72,BCW81..
2SC3052-F	Si-NPN	50V,0.2A,0.15W,200MHz	35a	Mit	BC846..847,BCW71..72,BCW81..
2SC3052-G	Si-NPN	50V,0.2A,0.15W,200MHz	35a	Mit	BC846..847,BCW71..72,BCW81..
2SC3053	Si-NPN	=2SC710:SMD	35a	Mit	BF799,BFS20,2SC3015
2SC3053-B	Si-NPN	-	35	Mit	→2SC3053
2SC3053-C	Si-NPN	-	35	Mit	→2SC3053
2SC3053-D	Si-NPN	-	35	Mit	→2SC3053
2SC3054	Si-N-Darl+Di	Sw,Pow,500/400V,20A,100W,<3/4µS	16c	Mat	BU932PFI,BUT13PFI
2SC3055	Si-NPN	Sw,Pow,Reg-Pow,450/400V,2A,15W,28MHz	17j$	Fui	BUX84..85,2SC2333,2SC2534,2SC2738,..
2SC3056	Si-NPN	Sw,Pow,Reg-Pow,450/400V,6A,50W,30MHz	17j$	Fui	MJE53T,2SC2518,2SC2542,2SC2827..
2SC3056A	Si-NPN	=2SC3056:450/450V	17j$	-	MJE53T,2SC2518,2SC2542,2SC2837..
2SC3057	Si-NPN	=2SC3045:50W	17j$	Fui	MJE13008,2SC3562,2SC4107,2SC4164
2SC3058	Si-NPN	Sw,Pow,Reg-Pow,600/400V,30A,200W,30MHz	23a$	Fujitsu	BUS14(A),BUS98(A)
2SC3058A	Si-NPN	=2SC3058:600/450V	23a$	-	BUS14(A),BUS98(A)
2SC3059	Si-NPN	Sw,Pow,Reg-Pow,1200/850V,2A,100W,15MHz	23a$	Fujitsu	BU204..206,MJ8500,2SC1132,2SD1097..
2SC306	Si-NPN	GenP,50V,0,5A,0,57W,240MHz,-/450nS	2a$	Mit	BC140..141,BC300..302,2N3053..

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2SC3060	Si-NPN	Sw,Pow,Reg-Pow,1200/850V,5A,100W,15MHz	23a$	Fujitsu	BU207..208(A),MJ8502,2SD1103..
2SC3061	Si-NPN	Sw,Pow,Reg-Pow,1200/850V,10A,200W,15MHz	23a$	Fujitsu	BU137A,MJ8504..8505,2SC3215
2SC3062	Si-NPN	UHF,25V,0,065A,0,4W,8,5GHz	52s	Nec	2SC3584
2SC3063	Si-NPN	Vid-Pow,300/300V,0,1A,140MHz	14h$	Mat	BF417,BF459,2SC3417,2SC3503..
2SC3064	Si-NPN	Dual,55V,0,15A,0,5W,100MHz	-	Sanyo	-
2SC3065	Si-NPN	Dual,55V,0,15A,0,5W,100MHz	-	Sanyo	-
2SC3066	Si-NPN	Dual,130V,0,05A,0,5W,130MHz	-	Sanyo	-
2SC3067	Si-NPN	Dual,130V,0,05A,0,5W,160MHz	-	Sanyo	-
2SC3068	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,30V,0,3A,B>800	7c	Sanyo	2SC3576,2SC3836
2SC3069	Si-NPN	Hi-beta,Hi-Ueb,60V,0,2A,B>800	7c	Sanyo	2SC2925,3SC3836,2SC3071
2SC307	Si-NPN	=2SC306:80V	2a$	Mit	BC140..141,BC300..301,2N1990..
2SC3070	Si-NPN	Hi-beta,Hi-Ueb,30V,1,2A,B>800	7c(9mm)	Sanyo	2SC4389,2SD1581..82,2SD1779
2SC3071	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,120V,0,2A,B>500	7c(9mm)	Sanyo	-
2SC3072	Si-NPN	AF,Sw-Pow,50V,5A,10W,100MHz	30j$	Tos	2SC3074,2SC3518,2SC3592,2SD1803..
2SC3073	Si-NPN	AF,Sw-Pow,30V,3A,15W,100MHz	30j$	Tos	2SC3386,2SC4681,2SD1221,2SD1802..
2SC3074	Si-NPN	AF,Sw-Pow,Lo-sat,60V,5A,20W,120MHz	30j$	Tos	2SC3303,2SC3518,2SC3592,2SD1803..
2SC3075	Si-NPN	Sw,Pow,500/400V,0,8A,10W,-/<4µS	30j$	Tos	2SC3363,2SC3632
2SC3076	Si-NPN	AF,Sw-Pow,Lo-sat,50V,2A,10W,80MHz	30j$	Tos	2SD1801..02,(2SD1078,2SD1221,..)
2SC3077	Si-NPN	VHF/UHF,30V,20mA,1100MHz	35a	Matsushita	BFS17,2SC3005,2SC3016,2SC3161
2SC3078(M)	Si-NPN	AM/FM,40V,0,1A,0,25W,230MHz	9c	Rhm	BF240..241,BF254..255,BF594..595,..
2SC3079(M)	Si-NPN	FM,25V,20mA,0,1SW,500MHz	9c	Rhm	BF225,BF310,BF314,BF502..503..
2SC308	Si-NPN	=2SC306:100V,90MHz	2a$	Mit	BC141,BC300,2N1889..90,2N1893(A),..
2SC3080(M)	Si-NPN	VHF-Mix/Osc,UHF-Osc,30V,50mA,1100MHz	9c	Rhm	BF377..378,BF689K,BF763,2N2857..
2SC3081	Si-NPN	VHF/UHF,30V,0,05A,1100MHz	7f	Rhm	BF377..378,BF689K,BF763,2N2857..
2SC3082	Si-NPN	VHF-Mix/Osc,UHF-0,30V,50mA,1100MHz	?35b	Rhm	-
2SC3082K	Si-NPN	=2SC3082:	35a	-	BF771,BFR35,2SC3014,2SC3016..
2SC3082K-M	Si-NPN	-	35	Rhm	→2SC3082K
2SC3082K-N	Si-NPN	-	35	Rhm	→2SC3082K
2SC3082K-P	Si-NPN	-	35	Rhm	→2SC3082K
2SC3082K-Q	Si-NPN	-	35	Rhm	→2SC3082K
2SC3083	Si-NPN	Sw,Pow,500/400V,6A,60W,<1/3,5µS	18j$	Sanyo	BUP22,TIPS8A,2SC2962,2SC3040..
2SC3084	Si-NPN	=2SC3083:70W	23a$	Sanyo	BUX15,2SD640,2SC2962,2SC3041,..
2SC3085	Si-NPN	Sw,Pow,500/400V,25A,160W,<1/3,5µS	23a$	Sanyo	BUS14(A),BUS98(A),2SC2930,2SC3058
2SC3086	Si-NPN	Sw,Pow,800/500V,3A,40W,<1/4µS	17j$	Sanyo	BUT11(A),BUV46(A),2SC3148,2SD841,..
2SC3087	Si-NPN	Sw,Pow,800/500V,5A,50W,<1/4µS	17j$	Sanyo	BUT11(A),BUV46(A),2SC3047,2SC3353..
2SC3088	Si-NPN	Sw,Pow,800/500V,4A,60W,<1/4µS	18j$	Sanyo	BU426(A),BUW11(A),2SC3448,2SC3796..
2SC3089	Si-NPN	Sw,Pow,800/500V,7A,80W,<1/4µS	18j$	Sanyo	BU426(A),BU926,2SC3449,2SC3536..
2SC309	Si-NPN	=2SC306:120V,120MHz	2a$	Mit	BC300,2N1893(A),2N2102,2N2405..
2SC3090	Si-NPN	Sw,Pow,800/500V,10A,100W,<1/4µS	18j$	Sanyo	BUW12(A),BUV47(A),2SC3450,2SC3637..
2SC3091	Si-NPN	Sw,Pow,800/500V,4A,70W	23a$	Sanyo	2SC3152,2SC3155,2SC3550,2SD802..
2SC3092	Si-NPN	Sw,Pow,800/500V,7A,90W	23a$	Sanyo	BU526,BU926,BUX47,2SC3449,2SD811+
2SC3093	Si-NPN	Sw,Pow,800/500V,10A,120W	23a$	Sanyo	BU626A,BUS12A,BUW35..36,2SC3637,..
2SC3094	Si-NPN	Sw,Pow,800/500V,20A,140W,<1/3,5µS	23a$	Sanyo	BUS14(A),BUS98(A),2SC3593
2SC3095	Si-NPN	UHF,25V,0,11A,2,75W,6,5GHz	62b$	Nec	-
2SC3096	Si-NPN	UHF,25V,0,22A,5,5W,6GHz	62b$	-	-
2SC3097	Si-NPN	-		Nec	-
2SC3098	Si-NPN	UHF,LN,30V,0,05A,3,5GHz	35a	Tos	BFT75,2SC3014,2SC3773
2SC3099	Si-NPN	UHF,LN,20V,0,03A,4GHz	35a	Tos	BFQ29,BFQ81,BFR93,BFT75
2SC31(S)	Si-NPN	VHF,60V,0,2A,0,75W,200MHz,B>20	2a$	Nec	BC140..141,BC300..302,2N3053..
2SC310	Si-NPN	=2SC306:140V,120MHz	2a$	Mit	BSS43,BSW68,2N1893A,2N3019..20
2SC3100	Si-NPN	-		Tos	-
2SC3101	Si-NPN	UHF-Dr/Out,35V,1A,Pq=3,5W(520MHz)	2a*	Mit	-
2SC3102	Si-NPN	UHF-Pow,35V,18A,Pq=65W(520MHz)	57s*	Mit	-
2SC3103	Si-NPN	UHF-Pow,20V,1,5A,Pq=3,2W(520MHz)	58s*	Mit	-
2SC3104	Si-NPN	UHF-Pow,20V,3A,Pq=7W(520MHz)	58s*	Mit	-
2SC3105	Si-NPN	UHF-Pow,35V,10A,Pq=35W(850MHz)	61v&	Mit	-
2SC3106	Si-NPN	UHF-Pow,36V,0,6A,Pq=2W(940MHz)	-	Mat	-
2SC3107	Si-NPN	UHF-Pow,36V,2A,Pq=5W(940MHz)	-	Mat	-
2SC3108	Si-NPN	UHF-Pow,36V,2A,Pq=14,5W(940MHz)	-	Mat	-
2SC3109	Si-NPN	UHF-Dr/Out,36V,0,3A,Pq=0,6W(940MHz)	51r	Mat	-
2SC311..312	Si-NPN	-		Fui	-
2SC3110	Si-NPN	UHF,15V,0,03A,4,5GHz	35a	Mat	BFR92..93,BFT75
2SC3111	Si-NPN	UHF,36V,0,1A,2W,2,5GHz	51r	Mat	BFG34,BFG96,2SC3368
2SC3112	Si-NPN	Hi-beta,50V,0,15A,0,4W,B=1500	7c	Tos	-

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2SC3113	Si-NPN	=2SC3112:0,2W	41c	-	-
2SC3114	Si-NPN	Hi-Ueb,60V,0,15A,0,4W,100MHz	7c	Sanyo	2SC3071,2SC3135,(BC546,..)
2SC3115	Si-NPN	GenP,LN,120V,0,05A,110MHz	35a	NEC	2SC1622A,2SC3324,2SC4050
2SC3115-D25	Si-NPN	-	35	Nec	→2SC3115
2SC3115-D26	Si-NPN	-	35	Nec	→2SC3115
2SC3115-D27	Si-NPN	-	35	Nec	→2SC3115
2SC3115-D28	Si-NPN	-	35	Nec	→2SC3115
2SC3116	Si-NPN	TV-AF-Pow,180/160V,0,7A,10W,120MHz	14h$	Sanyo	2SC3116..17,2SD669
2SC3117	Si-NPN	TV-AF-Pow,180/160V,1,5A,10W,120MHz	14h$	Sanyo	2SD669
2SC3118	Si-NPN	Sw,400/360V,0,15A,0,35W,<300/2300nS	2a$	Fuj	MPSA45,2SC2267,2SC3469,2SD1385
2SC3119	Si-NPN	UHF-TV-Tuner,AGC,25V,20mA,900MHz	35a	Tos	BFS17,2SC3015,2SC3161,2SC3374
2SC3120	Si-NPN	VHF/UHF-TV-Tuner,AGC,30V,2,4GHz	35a	Tos	BFR53,2SC3014,2SC3773
2SC3121	Si-NPN	UHF-Tuner,30V,0,05A,1,5GHz	35a	Tos	BFR53,2SC3013..3016,2SC3773
2SC3122	Si-NPN	VHF-TV-Tuner,AGC,30V,20mA,650MHz	35a	Tos	BF799,2SC3015,2SC3374
2SC3123	Si-NPN	TV-VHF-Mix,30V,0,05A,1,4GHz	35a	Tos	BFR53,2SC3014,2SC3016,2SC3773
2SC3124	Si-NPN	VHF-Osc,TV-Tuner,30V,1,1GHz	35a	Tos	BFR53,2SC3014..3016,2SC3773
2SC3125	Si-NPN	TV-IF-Out,30V,0,05A,600MHz	35a	Tos	(BF599,BF799,BFS20,2SC3014..3016)
2SC3126	Si-NPN	VHF/UHF,20V,0,05A,0,2W,4,5GHz	25za	Hit	BFP91,BFQ72,2SC3511
2SC3127	Si-NPN	-	35	Hit	→2SC3127
2SC3128	Si-NPN	=2SC3126:0,35W	7f	Hit	2SC2570(A),2SC3037,3SC3512
2SC3129L,S	Si-NPN	Sw,Pow,500/400V,0,5A,10W,<1/3,5µS	30j$	Hit	2SC3075,2SC3588,2SC3632,2SC4499
2SC313(H)	Si-NPN	VHF/UHF,30V,50mA,1000MHz	5g	Hit	BF377..378,BF689,BF763,2N2857..
2SC3130	Si-NPN	VHF/IF,15V,0,05A,1900MHz	35a	Mat	BFR53,2SC3014,2SC3016
2SC3130-P	Si-NPN	-	35	Mat	→2SC3130
2SC3130-Q	Si-NPN	-	35	Mat	→2SC3130
2SC3130-R	Si-NPN	-	35	Mat	→2SC3130
2SC3131	Si-NPN	Sw,Pow,600/400V,10A,100W,<1/5µS	23a$	Fjd	BU626A,BUW25..26,BUW35..36,2SD1094
2SC3132(L,S)	Si-NPN-Darl	AF,Sw-Pow,30V,3A,10W,B=10000	30j$	Hit	2SD1222..23,2SD1520,2SD1799,2SD1817
2SC3133	Si-NPN	AM-Pow,60V,6A,Pq=16W(27MHz)	17k*	Mit	2SC1945
2SC3134	Si-NPN	Hi-Ueb,60V,0,15A,100MHz	35a	Sanyo	(BC846,BCV71..72,2SC3324,..)
2SC3134-4	Si-NPN	-	35	Sanyo	→2SC3134
2SC3134-5	Si-NPN	-	35	Sanyo	→2SC3134
2SC3134-6	Si-NPN	-	35	Sanyo	→2SC3134
2SC3134-7	Si-NPN	-	35	Sanyo	→2SC3134
2SC3135	Si-NPN	Hi-Ueb,60V,0,2A,0,25W,100MHz	40c	Sanyo	2SC3071,2SC3114
2SC3136	Si-NPN	TV-VHF-M,30V,0,05A,1400MHz	7f	Tos	BF377..378,BF689K,BF763,2N2857..
2SC3137	Si-NPN	UHF,30V,0,05A,0,2W,2400MHz	25u	Sanyo	2SC2464,2SC2466,2SC2353,2SC2728
2SC3138	Si-NPN	Sw,200V,0,05A,100MHz	35a	Toshiba	BF820,BF822,BFN22,2SC3360
2SC3138-O	Si-NPN	-	35	Tos	→2SC3138
2SC3138-Y	Si-NPN	-	35	Tos	→2SC3138
2SC3139	Si-NPN	UHF-Pow,50V,1A,Pq=2,4W(900MHz)	55s	Nec	BLW33
2SC314	Si-NPN	AF/HF/Sw,75V,1,2A,20W,70MHz	2a$	Hit	(BD139,BD230,BD377,2SD1177..1178)
2SC3140	Si-NPN	UHF-Pow,50V,2A,Pq=5,4W(900MHz)	55s	Nec	BLW98
2SC3141	Si-NPN	UHF-Pow,50V,4A,Pq=10,7W(900MHz)	55s	Nec	2N4431
2SC3142	Si-NPN	FM/VHF,25V,0,03A,750MHz	35a	Sanyo	BF599,BF799,2SC3015,2SC3374
2SC3142-2	Si-NPN	-	35	Sanyo	→2SC3142
2SC3142-3	Si-NPN	-	35	Sanyo	→2SC3142
2SC3142-4	Si-NPN	-	35	Sanyo	→2SC3142
2SC3143	Si-NPN	GenP,180/160V,0,08A,150MHz	35a	Sanyo	BFN24,BFN26,2SC3360
2SC3143-3	Si-NPN	-	35	Sanyo	→2SC3143
2SC3143-4	Si-NPN	-	35	Sanyo	→2SC3143
2SC3143-5	Si-NPN	-	35	Sanyo	→2SC3143
2SC3144	Si-N-Darl+Di	Sw,Pow,70V,3A,20W,200MHz,B=5000	17j$	Sanyo	(BDT61A..C,BDW53B..D)
2SC3145	Si-N-Darl+Di	Sw,Pow,70V,5A,30W,200MHz,B=5000	17j$	Sanyo	(BDT63A..C,BDX33B..D)
2SC3146	Si-N-Darl+Di	Sw,Pow,70V,7A,40W,B=5000	17j$	Sanyo	BDT63A..C,BDX33B..D
2SC3147	Si-NPN	VHF-Pow,36V,14A,Pq=60W(175MHz)	57s$	Tos	BLV75/12,MRF245
2SC3148	Si-NPN	Sw,Pow,Lo-sat,900/800V,3A,40W	17j$	Tos	-
2SC3149	Si-NPN	Sw,Pow,900/800V,1,5A,40W,15MHz	17j$	Sanyo	BUV36A,BUX85,2SC3491,2SC3531..
2SC315(H)	Si-NPN	=2SC314:80MHz	2a$	Hit	(BD139,BD230,BD377,2SD1177..1178)
2SC3150	Si-NPN	Sw,Pow,900/800V,3A,40W,15MHz	17j$	Sanyo	BUT11A,BUV46A,2SC3490..3491..
2SC3151	Si-NPN	Sw,Pow,900/800V,1,5A,60W,15MHz	18j$	Sanyo	BUW11A,2SC3285,2SC3152,2SC3550..
2SC3152	Si-NPN	Sw,Pow,900/800V,3A,80W,15MHz	18j$	Sanyo	BUW11A,2SC3285,2SC3152,2SC3550..
2SC3153	Si-NPN	Sw,Pow,900/800V,6A,100W,15MHz	18j$	Sanyo	BUW11A,BUW131A,2SC3535,2SC3796A..
2SC3154	Si-NPN	=2SC3151:70W	23a$	Sanyo	BUS11A,BUW11A,BUX46A,2SC3285..

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2SC3155	Si-NPN	=2SC3152: 90W	23a$	Sanyo	BUS11A, BUW11A, BUX46A, 2SC3285..
2SC3156	Si-NPN	=2SC3153: 120W	23a$	Sanyo	BUS11A, BUX47A, BUX83, 2SD811..
2SC3157	Si-NPN	Sw, Pow, 150/100V, 10A, 60W, <0,5/2µS	15j$	Nec	BD743E, 2SC4330
2SC3158	Si-NPN	Sw, Pow, 500/400V, 7A, 60W, <1/3,5µS	15j$	Nec	MJE13006, 2SC2335, 2SC3170, 2SC4106..
2SC3159	Si-NPN	Sw, Pow, 500/400V, 10A, 80W, <1/3,2µS	15j$	Nec	MJE13008..09, 2SC3562, 2SC4107..
2SC316	Si-NPN	GenP, LN, 45V, 0,03A, 0,3W, 50MHz	2a$	Mat, Mic	BC184, BC413..414, BC550, 2SC2240..
2SC3160	Si-NPN+Diode	Sw, Pow, 200/100V, 7,5A, 40W, <2/4µS	15j$	Nec	BU406D..408D, 2SC3174, 2SC3176
2SC3161	Si-NPN	UHF, 25V, 0,07A, 5GHz	35a	Fui	2SC2845, 2SC3704, 2SC3774
2SC3162	Si-NPN	Sw, Pow, 500/400V, 3A, 40W, <300/1100nS	17j$	Shi	BUT11(A), BUT93, TIP75C, 2SC4105..
2SC3163	Si-NPN	Sw, Pow, 500/400V, 6A, 50W, <300/1100nS	17j$	Shi	MJE13006, 2SC2827, 2SC4055, 2SC4106..
2SC3164	Si-NPN	Sw, Pow, 500/400V, 10A, 100W, <300/1100nS	16j$	Shi	BUP23, 2SC3435, 2SC4138, 2SC4434..
2SC3165	Si-NPN	Sw, Pow, 500/400V, 3A, 60W, <300/1100nS	22a$	Shi	BUT93, BUY63..64, 2SC1467, 2SC2826..
2SC3166	Si-NPN	Sw, Pow, 500/400V, 6A, 80W, <300/1100nS	22a$	Shi	MJE13070, 2SC3170, 2SC4055, 2SC4106..
2SC3167	Si-NPN	Sw, Pow, 500/400V, 10A, 100W, <300/1100nS	23a$	Shidengen	BUW25..26, BUW34..36, 2SC3046..
2SC3168	Si-NPN	Sw, Pow, 500/400V, 20A, 200W, <300/1100nS	23a$	Shidengen	2SC3085, 2SC3094, 2SC3593
2SC3169	Si-NPN	Sw, Pow, 500/400V, 2A, 25W, <1/4µS	17c	Mat	BUX84F..85F, 2SC4421, 2SC4533..
2SC317(H)	Si-NPN	Sw, 70V, 0,1A, 0,35W, <80/200nS	2a	Hit	BF297..299, BFR86, BSS38, BSX21..
2SC3170	Si-NPN	Sw, Pow, 500/400V, 7A, 40W, <1/4µS	17c	Mat	BU306F, 2SC3571, 2SC4161, 2SC4559..
2SC3171	Si-NPN	Sw, Pow, 500/400V, 10A, 100W, <1/4µS	18j$	Mat	BUP23, 2SC3435, 2SC4434, 2SC4138..
2SC3172	Si-NPN	UHF, 30V, 0,05A, 0,2W, 1400MHz	25za	Tos	2SC2465, 2SC2470, 2SC2368
2SC3173	Si-NPN	TV-HD, Hi-def, 330/150V, 7A, 50W, 40MHz	17j$	Sanyo	BU406..408, 2SC3590..91, 2SD884..885
2SC3174	Si-NPN+Diode	=2SC3173: integr. Damper-Di	17j$	Sanyo	BU104DP, BU406D..408D
2SC3175	Si-NPN	=2SC3173: 400/200V	17j$	Sanyo	BU104P, BU406, BU408, 2SC3591
2SC3176	Si-NPN+Diode	=2SC3174: integr. Damper-Di, 400/200V	17j$	Sanyo	BU104DP, BU406D, BU408D
2SC3177	Si-NPN	UHF, 15V, 0,05A, 0,25W, 1900MHz	7c	Mat	BF357, BF377..378, 2SC2570(A)..
2SC3178	Si-NPN	=2SC3059: 60W	17j$	Fui	BUS05, MJE8500..8501, 2SC4230
2SC3179	Si-NPN	AF, Sw-Pow, Lo-sat, 80V, 4A, 30W, 15MHz	17j$	Sak	2SC3253, 2SD1236L, (BDS37, BD539B,..)
2SC317A	Si-NPN	=2SC317: 100V, 180MHz	2a	-	BF297..299, BFR86, BSS38, BSX21..
2SC318(A)	Si-NPN	HF/GenP, 50V, 0,1A, 0,3W, 170MHz	2a$	Son	BC237, BC547, 2N2221..22, 2N3903..04..
2SC3180	Si-NPN	AF, Sw-Pow, 80V, 6A, 60W, 30MHz	18j$	Tos	BD245B, BDV93, 2SC2706, 2SC2837..
2SC3180N	Si-NPN	80V, 6A, 60W, 30MHz	-		-
2SC3181	Si-NPN	=2SC3180: 120V, 8A, 80W	18j$	Tos	BD245C, 2SC2681, 2SC2837, 2SC2987(A),..
2SC3181N	Si-NPN	120V, 8A, 80W, 30MHz	-		-
2SC3182	Si-NPN	=2SC3180: 140V, 10A, 100W	18j$	Tos	BD245D, 2SC2706, 2SC2837, 2SD1047,..
2SC3182N	Si-NPN	140V, 10A, 100W, 30MHz	-		-
2SC3183	Si-NPN	Sw, Pow, 900/800V, 0,2A, 25W, 15MHz	17j$	Sanyo	2SC3149, 2SC3675..76, 2SD1527
2SC3184	Si-NPN	Sw, Pow, 900/800V, 0,5A, 30W, 15MHz	17j$	Sanyo	2SC3149, 2SC3456, 2SC3676, 2SD1527
2SC3185	Si-NPN	UHF-Dr/Out, 35V, 0,4A, Pq=1,4W(500MHz)	2a$	Nec	BFS50, MRF629, 2N3948, 2SC2762
2SC3186	Si-NPN-Darl	Sw, Pow, 200/200V, 3A, 30W, 60MHz, B=2000	17j$	Sak	2SD834, 2SD1073, 2SD1085, 2SD1121..
2SC3187	Si-NPN	Vid, 300/300V, 0,1A, 0,75W, 140MHz	7c	Mat	BF299, BF393, BF420A, 2SC3468..
2SC3189	Si-NPN	TV-HD, Hi-def, 250/100V, 7,5A, 50W	17j$	Sanyo	BU406..408, 2SC3173, 2SC3175..
2SC319	Si-NPN	VHF-A/Dr, 40V, 0,3A, Pq=1,2W(200MHz)	2a$	Nec	BFR98, BFX55, BLW16, MRF225..
2SC3190	Si-NPN	HF, 35V, 0,1A, 0,4W, 120MHz	7c	Kec	BC238, BC548, BF920..921(S), BF959..
2SC3191	Si-NPN	=2SC3190: 0,2W	41c	Kec	BC238, BC548, BF920..921(S), BF959..
2SC3192	Si-NPN	FM-IF, 35V, 0,05A, 175MHz	7c	Kec	BF240..241, BF254..255, BF594..595,..
2SC3193	Si-NPN	=2SC3192:	41c	Kec	BF240..241, BF254..255, BF594..595,..
2SC3194	Si-NPN	FM-Preamp, 40V, 0,02A, 550MHz	7c	Kec	BF225, BF241, BF255, BF314, BFS02..
2SC3195	Si-NPN	=2SC3194:	41c	Kec	BF225, BF241, BF255, BF314, BFS02..
2SC3196	Si-NPN	TV-IF-AGC, 40V, 0,05A, 530MHz	7c	Kec	BF198, BF225, BF310, BF367, BFS96..
2SC3197	Si-NPN	TV-IF, 30V, 0,05A, 660MHz	7c	Kec	BF198..199, BF224..225, BF596..597,..
2SC3198	Si-NPN	GenP, LN, 60V, 0,15A, 0,4W, 130MHz	7c	Kec	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,..
2SC3199	Si-NPN	=2SC3198: 0,2W	41c	Kec	2SC1775(A), 2SC2240, 2SC2390, 2SC2459,..
2SC32(A,AN,M,N)	Si-NPN	=2SC32: B>40	2a$	Nec, Mic	BC140..141, BC300..302, 2N3053..
2SC320	Si-NPN	VHF-A/Dr, 40V, 0,5A, Pq=2,4W(200MHz)	2a$	Nec	BFS22, BFW46, BLY33, MRF237, 2N3924
2SC3200	Si-NPN	AF, LN, 120V, 0,1A, 0,3W, 100MHz	7c	Kec	2SC1775A, 2SC2240, 2SC2362, 2SC2459,..
2SC3201	Si-NPN	=2SC3200: 0,2W	41c	Kec	2SC1775A, 2SC2240, 2SC2362, 2SC2459,..
2SC3202	Si-NPN	GenP, 35V, 0,5A, 0,3W, 300MHz	7c	Kec	BC337..338, BC635, BC637, 2SC3377..
2SC3203	Si-NPN	GenP, 35V, 0,8A, 0,6W, 120MHz	7c	Kec	BC337..338, BC635, BC637, 2SD2322S,..
2SC3204	Si-NPN	=2SC3203: 0,3W	41c	Kec	→2SC3203
2SC3205	Si-NPN	AF-Dr/Out, 30V, 2A, 1W, 120MHz	7c(9mm)	Kec	2SC3328, 2SD1014, 2SD1146, 2SD1207..
2SC3206	Si-NPN	AF/Vid, 200V, 0,05A, 0,8W, 120MHz	7c(9mm)	Kec	BF422(A), 2SC3467..69, 2SC3249
2SC3207	Si-NPN	AF/Vid, 300V, 0,1A, 0,9W, 70MHz	7c(9mm)	Kec	2SC3468..69, 2SC3249, (BF459, 2SC4019+)
2SC3208	Si-NPN	Sw, Pow, 300/300V, 0,15A, 100MHz	17j$	Kec	2SC1505..1507, 2SC1755..1757, 2SC1905
2SC3209	Si-NPN	CTV-Vid-Out, 300/300V, 0,2A, 1W, 50MHz	9b	NEC	BF299, BF393, BFR89, 2SC3468..

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2SC321	Si-NPN	HF/Sw,40V,0,2A,0,36W,20/25nS,B>30	2a$	Hit	BSS11,BSX19..20,2N2368..69(A)..
2SC3210	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/3,5µS	16c	Mat	2SC4297,2SC4423
2SC3211	Si-NPN	Sw,Pow,800/500V,5A,70W,<1/4µS	16c	Mat	BUW11(A)F;2SC4300,2SC4457..58
2SC3211A	Si-NPN	=2SC3211:900/500V,<1,2/4,2µS	16c	-	BUW11AF,2SC4300,2SC4586
2SC3212	Si-NPN	Sw,Pow,800/500V,7A,100W,<1/3,5µS	16c	Mat	BUV47(A)FI,BUW12(A)F,2SC4301
2SC3212A	Si-NPN	=2SC3212:900/500V,<1,2/3,7µS	16c	-	BUV47AFI,BUW12AF,2SC4301
2SC3213	Si-NPN	Sw,Pow,800/400V,75A,300W,<1,5/4,5µS	-	Org	-
2SC3214	Si-NPN	Sw,Pow,1200/800V,5A,80W	23a$	Org	MJ8502..8503,2SC3060,2SC3343,2SC3387
2SC3215	Si-NPN	Sw,Pow,1200/800V,10A,125W,<1/5µS	23a$	Org	BUV48B,C,MJ8504..8505,2SC3061..
2SC3216	Si-NPN	Sw,Pow,1200/800V,20A,200W	23a$	Org	-
2SC3217	Si-NPN	Dual,UHF-Pow,50V,12A,Pq=10W(860MHz)	?61	Nec	-
2SC3218	Si-NPN	Dual,UHF-Pow,55V,15A,Pq=60W(860MHz)	?61	Nec	-
2SC3219	Si-NPN	Sw,Pow,230/230V,6A,50W,<300/600nS	17j$	Shi	BU409,MJE51T..53T,2SC2767..
2SC322	Si-NPN	=2SC321:B=40	2a$	Hit	BSS11,BSX19..20,2N2368..69(A)..
2SC3220	Si-NPN	Sw,Pow,230/230V,10A,100W,<300/600nS	16c(j$)	Shi	TIP160..162,2SC2729,2SC2944..
2SC3221	Si-NPN	Sw,Pow,230/230V,6A,80W,<300/600nS	22a$	Shi	BU409,TIP150..152,2SC1987,2SC2767..
2SC3222	Si-NPN	Sw,Pow,230/230V,10A,100W,<300/600nS	23a$	Shidengen	BUX17(A..C),BUX42..43,2SC2944..
2SC3223	Si-NPN	Sw,Pow,230/230V,20A,200W,<300/600nS	23a$	Shidengen	BUV11..12,BUW58,BUW73,BUX11..12
2SC3224	Si-NPN	Sw,Pow,230/230V,30A,300W,<300/600nS	68a$	Shi	2SC1301,2SC2249,2SC2445,2SC2940..
2SC3225	Si-NPN	Hi-beta,Lo-sat,40V,2A,220MHz,B>500	7c(9mm)	Tos	-
2SC3226	Si-NPN	AF-Dr/Out,30V,2A,0,9W,150MHz	7c(9mm)	Kec	2SC3328,2SD1014,2SD1146,2SD1207..
2SC3227	Si-NPN	AF-Dr/Out,80V,0,4A,0,8W,100MHz	7c(9mm)	Kec	2SC3939,2SD667(A),2SD1937,2SD1211..
2SC3228	Si-NPN	AF-Dr/Out,160/160V,1A,0,9W,120MHz	7c(9mm)	Kec	2SC2383,2SD1812
2SC3229	Si-NPN	AF/Vid-Pow,300/300V,0,05A,95MHz	13j$	KEC	(BF583,BF617,BF758..759,BF859,..)
2SC323	Si-NPN	GenP,40V,0,1A,0,25W,250MHz	2a$	Tos	BC167,BC183,BC237,BCS47,2SD767..
2SC3230	Si-NPN	AF,Sw-Pow,30V,3A,10W,100MHz	17j$	Kec	2SC1173,2SC2562,2SC3252..3253..
2SC3231	Si-NPN	AF,Sw-Pow,200V,4A,40W,8MHz,<3/9,5µS	17j$	Kec	BD243F,2SC2767,2SD772A,B
2SC3232	Si-NPN	Sw,Pow,900/400V,6A,80W,<0,5/4µS	16j$	Nec	BU426A,BUW11A,2SC3535,2SC3796A..
2SC3233	Si-NPN	Sw,Pow,500/400V,2A,20W,<1/3,5µS	30j$	Tos	2SC3631,(BUV93..95)
2SC3234	Si-NPN	TV-VD-Out,150/150V,1,5A,25W,4MHz	?15j$	Tos	2SC1669,2SC2073,2SD608(A),2SD1138..
2SC3235	Si-NPN	Sw,Pow,500/400V,2A,20W,<1/3,5µS	?15j$	Tos	BUX84..85,2SC2333,2SC2534,2SC2738,..
2SC3236	Si-NPN	Sw,Pow,500/400V,5A,60W,<1/3,5µS	?15j$	Tos	MJE13070,2SC2535,2SC2827,2SC3830..
2SC3237	Si-NPN	AF,Sw-Pow,30V,3A,20W,100MHz	?15j$	Tos	2SC1173,2SC2562,2SC3252..53,2SD1505
2SC3238	Si-NPN	AF,Sw-Pow,160V,1,5A,25W,100MHz	?15j$	Tos	2SC2238(A,B),2SC2344,2SD608(A)..
2SC3239	Si-NPN	Lo-sat,60V,5A,25W,120MHz	?15j$	Tos	2SC2562,2SC3253..54,2SC3258
2SC324	Si-NPN	HF,20V,25mA,0,2W,180MHz	2a$	Fui	BF240..241,BF254..255,BF594..595,..
2SC3240	Si-NPN	AM-Pow,50V,25A,Pq=110W(30MHz)	59r*	Mit	2SC2879
2SC3241	Si-NPN	AM-Pow,50V,18A,Pq=85W(30MHz)	59r*	Mit	MRF421,MRF454
2SC3242	Si-NPN	20V,2A,0.9W,80MHz	-		-
2SC3242(A)	Si-NPN	GenP,20V,2A,0,9W,80MHz	7c(9mm)	Mit	2SC3226,2SD787..788,2SD1146,2SD1207..
2SC3243	Si-NPN	GenP,60V,1A,0,9W,120MHz	7c(9mm)	Mit	2SD667,2SD863,2SD1207,2SD1292..
2SC3244	Si-NPN	GenP,100V,0,5A,0,9W,130MHz	7c(9mm)	Mit	2SC1670,2SC2235,2SD1211,2SD1937
2SC3244E	Si-NPN	100V,0.5A,0.9W,130MHz	-		-
2SC3245	Si-NPN	GenP,120/120V,0,1A,0,9W,200MHz	7c(9mm)	Mit	2SC2631..32,2SC3248,2SC3800
2SC3245A	Si-NPN	=2SC3245:150/150V	7c(9mm)	-	2SC2632,2SC3248,2SC3800
2SC3246	Si-NPN	Lo-sat,30V,1,5A,0,9W,130MHz,B>400	7c(9mm)	Mit	2SC3225,2SC4389
2SC3247	Si-NPN	Lo-sat,50V,1A,0,9W,130MHz,B>600	7c(9mm)	Mit	(2SC3225)
2SC3248	Si-NPN	GenP,180/180V,0,1A,0,9W,130MHz	7c(9mm)	Mit	BF422A,2SC3467..69,2SC3249
2SC3249	Si-NPN	Vid,300/250V,0,1A,0,9W,80MHz	7c(9mm)	Mit	BF420A,2SC3468..69,2SC4166
2SC325	Si-NPN	UHF,12V,0,05A,0,25W,1000MHz	5g	Oki	BFR37,BFW30,BFX73,2SC2570(A)..
2SC3250	Si-NPN	Vid-Out,300/300V,0,1A,15W,100MHz	17l&	Mat	(2SC1505..1507,2SC1755..1757,2SC1905)
2SC3251	Si-NPN	HF-Pow,55V,0,4A,15W,700MHz	17f*	Mat	-
2SC3252	Si-NPN	AF,Sw-Pow,80V,3A,30W,100MHz	17j$	Sanyo	BDV10..12,MJE15028,2SC3259
2SC3253	Si-NPN	AF,Sw-Pow,Lo-sat,80V,5A,30W,100MHz	17j$	Sanyo	2SC3258
2SC3254	Si-NPN	AF,Sw-Pow,Lo-sat,80V,7A,35W,100MHz	17j$	Sanyo	2SC3346
2SC3255	Si-NPN	AF,Sw-Pow,Lo-sat,80V,10A,40W,100MHz	17j$	Sanyo	2SC3346
2SC3256	Si-NPN	AF,Sw-Pow,Lo-sat,80V,15A,70W,100MHz	18j$	Sanyo	(2SD1238L,2SD1840)
2SC3257	Si-NPN	Sw,Pow,250/200V,10A,40W,<1/3,5µS	17j$	Tos	BUS36..37,BUV27(A),2SC2867
2SC3258	Si-NPN	Sw,Pow,Lo-sat,100/80V,5A,30W,120MHz	17j$	Tos	-
2SC3259	Si-NPN-Darl	Sw,Pow,800/800V,3A,40W,B=10	17j$	Shi	(BUD46(A))
2SC326	Si-NPN	UHF,20V,0,05A,0,25W,1000MHz	5g	Oki	BFR37,BFW30,BFX73,2SC2570(A)..
2SC3260	Si-NPN-Darl	=2SC3259:50W	16j$	Shi	2SC3472
2SC3261	Si-NPN-Darl	Sw,Pow,800/800V,6A,80W,B=10	16j$	Shi	2SC3030,2SC3032
2SC3262	Si-NPN-Darl	Sw,Pow,800/800V,10A,100W,B=10	16j$	Shi	(BUT51P)

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2SC3263	Si-NPN	AF,Sw-Pow,230/230V,15A,130W,60MHz	18j$	Sak	2SC2944,2SC5358
2SC3264	Si-NPN	AF,Sw-Pow,230/230V,17A,200W,60MHz	20j$	Sak	2SC3436
2SC3265	Si-NPN	GenP,Lo-sat,35V,0,8A,120MHz	35a	Toshiba	BCW65..66
2SC3265-O	Si-NPN	-	35	Tos	→2SC3265
2SC3265-Y	Si-NPN	-	35	Tos	→2SC3265
2SC3266	Si-NPN	GenP,20V,2A,0,75W,120MHz	7c	Tos	MPS650,2SC3205,2SC3226,2SD1207..
2SC3267	Si-NPN	=2SC3266:0,4W	41c	Tos	MPS650,2SC3205,2SC3226,2SD1207..
2SC3268	Si-NPN	VHF/UHF,17V,0,07A,0,3W,5GHz	39b	Tos	BFQ19,2SC3301
2SC3269	Si-NPN	Vid,300/300V,0,1A,0,75W,100MHz	7c(9mm)	Rhm	BF420A,2SC3249,2SC3468..69,2SC4166
2SC327	Si-NPN	UHF,30V,0,05A,0,25W,1000MHz	5g	Oki	BFR37,BFW30,BFX73,2SC2570(A)..
2SC3270(M)	Si-NPN	=2SC3269:	9c,41c	Rhm	→2SC3269
2SC3271	Si-NPN	=2SC3269:5W	14b	Rhm	2SC3789..90,2SC4828
2SC3272	Si-NPN	=2SC3269:10W	14h$	Rhm	BF417,BF459,2SC2621,2SC3417..
2SC3273	Si-NPN	UHF,15V,0,05A,0,4W,2,5GHz	7c	Mat	2SC2498,2SC2570(A),2SC3037
2SC3274	Si-NPN	UHF,15V,0,05A,0,4W,1,3GHz	7c	Mat	BF357,2SC2498,2SC2570(A),2SC3037
2SC3275	Si-NPN	UHF,15V,0,05A,0,4W,1,8GHz	7c	Mat	BF357,2SC2498,2SC2570(A),2SC3037
2SC3276	Si-NPN	UHF,15V,0,03A,0,35W,7GHz	25u	Mat	BFG65,BFQ182,2SC1923,2SC3062
2SC3277	Si-NPN	Sw,Pow,500/400V,10A,90W,20MHz	18j$	Sanyo	BUP23,2SC3042,2SC4138,2SC4434..
2SC3278	Si-NPN	=2SC3277:100W	23a$	Sanyo	BUS12(A),BUW25..26,BUW34..36,.
2SC3279	Si-NPN	GenP,Lo-sat,30V,2A,0,75W,150MHz	7c	Tos	MPS650,2SC3205,2SC3226,2SD1207..
2SC328	Si-NPN	UHF,30V,0,02A,0,2W,1500MHz	5g	Oki	BFR37,BFW30,BFX73,2SC2570(A)..
2SC3280	Si-NPN	AF-Out,160/160V,12A,120W,30MHz	77j$	Tos	2SC4029,2SD1704,2SD1717..18,2SD2029..
2SC3281	Si-NPN	AF-Pow,200/200V,15A,150W,30MHz	77j$	Tos	2SC4029
2SC3282(A)	Si-NPN	UHF-Pow,35V,7,5A,Pq=23W(860MHz)	61v	Nec	BLV95,MRF844
2SC3283(A)	Si-NPN	UHF-Pow,35V,15A,Pq=37W(860MHz)	61v	Nec	-
2SC3284	Si-NPN	AF,Sw-Pow,150/150V,14A,125W,60MHz	18j$	Sak	2SC2987(A),2SC3907,2SD1047,2SD1703
2SC3285	Si-NPN	Sw,Pow,1000/800V,3A,70W,<1/3µS	18j$	Mat	BUW11A,BUW131A,2SC3459,2SC3533..35
2SC3286	Si-NPN	VHF-Pow,55V,24A,Pq=126W(230MHz)	?61	Nec	-
2SC3287	Si-NPN	UHF,36V,0,1A,Pq=80mW(915MHz)	25za	Mat	2SC3368
2SC3288	Si-NPN	UHF,36V,0,3A,Pq=0,35W(915MHz)	25za	Mat	2SC3369,2SC3019
2SC3289	Si-NPN	UHF-Pow,36V,0,6A,Pq=1,5W(915MHz)	-	Mat	-
2SC329	Si-NPN	UHF,30V,0,02A,0,2W,1500MHz	5g	Oki	BFR37,BFW30,BFX73,2SC2570(A)..
2SC3290	Si-NPN	UHF-Pow,36V,2A,Pq=6,5W(915MHz)	-	Mat	-
2SC3291	Si-NPN	UHF-Pow,36V,3A,Pq=17W(915MHz)	-	Mat	-
2SC3292	Si-N-Darl+Di	Sw,Pow,50V,1,2A,20W,180MHz,B=4000	17j$	Sanyo	-
2SC3293	Si-N-Darl+Di	Sw,Pow,50V,2A,20W,180MHz,B=4000	17j$	Sanyo	-
2SC3294	Si-N-Darl+Di	Sw,Pow,50V,3A,25W,180MHz,B=4000	17j$	Sanyo	-
2SC3295	Si-NPN	Hi-beta,50V,0,15A,250MHz,B>600	35a	Toshiba	2SC3624
2SC3295-A	Si-NPN	-	35	Tos	→2SC3295
2SC3295-B	Si-NPN	-	35	Tos	→2SC3295
2SC3296	Si-NPN	TV-VD,Pow,150/150V,1,5A,20W,4MHz	17c	Tos	2SC3298(A,B),2SC3364,2SC3567,2SC4159
2SC3297	Si-NPN	AF,Sw-Pow,30V,3A,15W,100MHz	17c	Tos	2SC3299,2SC4369,2SD1913
2SC3298	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,100MHz	17c	Tos	2SC3364,2SC4159,2SC4370,2SC4883A
2SC3298A	Si-NPN	=2SC3298:180V	17c	-	2SC4159,2SC4883A
2SC3298B	Si-NPN	=2SC3298:200V	17c	-	2SC4793
2SC3299	Si-NPN	DC-DCConv.,Lo-sat,60V,5A,20W,120MHz	17c	Tos	2SC3746..47,2SC4881
2SC33	Si-NPN	HF,45V,50mA,250MHz	5g	Nec	BF184..185,BF240..241,BF254..255..
2SC330	Si-NPN	UHF,20V,0,02A,0,2W,3500MHz	24f	Oki	BFR34,BFT97,BFQ59..60,BFQ70
2SC3300	Si-NPN	Sw,Pow,Lo-sat,100V,15A,100W	18j$	Sak	2SD1840
2SC3301	Si-NPN	UHF,15V,0,08A,7GHz	39b	Tos	2SC3357,2SC4988
2SC3302	Si-NPN	UHF,17V,0,07A,7GHz	25za	Tos	BFG195,BFQ73,2SC3358,2SC3603
2SC3303	Si-NPN	AF,Sw-Pow,Lo-sat,100V,5A,20W,120MHz	30j$	Tos	-
2SC3304	Si-NPN	Sw,Pow,250/200V,10A,40W,<1/3,5µS	?15j$	Tos	BUS36..37,BUV27(A),2SC2867
2SC3305	Si-NPN	Sw,Pow,900/800V,3A,40W,<1/5µS	?15j$	Tos	BUT11(A),BUV46(A),2SC3490..3491..
2SC3306	Si-NPN	Sw,Pow,500/400V,10A,100W,<1/3,5µS	18j$	Tos	BUP23,2SC3042,2SC4138,2SC4434..
2SC3307	Si-NPN	Sw,Pow,900/800V,10A,150W,<1/4µS	77j$	Tos	2SC3910,2SC3982,2SC3992
2SC3308	Si-NPN	Sw,Pow,Lo-sat,100V,5A,30W,120MHz	?15j$	Tos	2SC3258
2SC3309	Si-NPN	Sw,Pow,500/400V,2A,20W,-/<3,5µS	17c	Tos	BUX84F..85F,2SC4421,2SC4533..
2SC331	Si-NPN	UHF,20V,0,02A,0,2W,3500MHz	24f	Oki	BFR34,BFT97,BFQ59..60,BFQ70
2SC3310	Si-NPN	Sw,Pow,500/400V,5A,30W,-/<3,5µS	17c	Tos	2SC3497,2SC4073,2SC4371,2SC4418..
2SC3311	Si-NPN	GenP,30V,0,1A,0,3W,150MHz	40c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SC3311A	Si-NPN	=2SC3311:60V	40c	-	BC167,BC182,BC237,BC547,2SD767..
2SC3312	Si-NPN	GenP,LN,60V,0,1A,0,3W,200MHz	40c	Mat	BC414,BC550,2SC1775(A),2SC2390..
2SC3313	Si-NPN	AM/FM,30V,0,03A,0,3W,250MHz	40c	Mat	BF240..241,BF254..255,BFS94..595,..

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2SC3314	Si-NPN	AM/FM,30V,0,03A,0,3W,300MHz	40c	Mat	BF198..199,BF224..225,BF596..597,..
2SC3315	Si-NPN	AM/FM,30V,15mA,0,3W,650MHz	40c	Mat	BF225,BF314,BF502,BF505,BF507..
2SC3316	Si-NPN	Sw,Pow,500/400V,2A,40W,<500/1650nS	17j$	Fjd	BUX84..85,2SC2333,2SC2534,2SC2738,..
2SC3317	Si-NPN	Sw,Pow,500/400V,5A,40W,<500/1650nS	17j$	Fjd	MJE13070,2SC2535,2SC2827,2SC3830..
2SC3318	Si-NPN	Sw,Pow,500/400V,10A,80W,<500/1650nS	18j$	Fjd	BUP23,2SC2828,2SC3042,2SC4138..
2SC3319	Si-NPN	Sw,Pow,500/400V,10A,100W,<500/1650nS	23a$	Fujitsu	BUW25..26,BUW34..36,2SC3046..
2SC332	Si-NPN	HF/Sw,30V,0,2A,0,15W,450MHz	5g	Oki	BSS11,BSX19..20,2N2368..69(A)..
2SC3320	Si-NPN	Sw,Pow,500/400V,15A,80W,<500/1650nS	18j$	Fjd	BUP23,2SC3520,2SC4139,2SC4434..
2SC3321	Si-NPN	Sw,Pow,500/400V,15A,100W,<500/1650nS	23a$	Fujitsu	BUV25,BUW44,BUX25,2SD641..
2SC3322	Si-NPN	Sw,Pow,900/800V,5A,80W,<1/4µS	18j$	Hit	BUW11A,2SC3153,2SC3232,2SC3535..
2SC3323	Si-NPN	AF,LN,60V,0,15A,150MHz	35a	Tos	2SC3323..24
2SC3324	Si-NPN	AF,LN,120V,0,1A,100MHz	35a	Tos	2SD814
2SC3324-BL	Si-NPN	-	35	Tos	→2SC3324
2SC3324-GR	Si-NPN	-	35	Tos	→2SC3324
2SC3325	Si-NPN	GenP,50V,0,5A,300MHz	35a	Toshiba	BC817,BCX19,2SC3441
2SC3325-O	Si-NPN	-	35	Tos	→2SC3325
2SC3325-Y	Si-NPN	-	35	Tos	→2SC3325
2SC3326	Si-NPN	Hi-Ueb,50V,0,3A,30MHz	35a	Tos	2SC3134
2SC3326A	Si-NPN	-	35	Tos	→2SC3326A
2SC3326B	Si-NPN	-	35	Tos	→2SC3326B
2SC3327	Si-NPN	=2SC3326:	41c	-	2SC2878
2SC3328	Si-NPN	GenP,Lo-sat,80V,2A,0,9W,100MHz	7c(9mm)	Tos	2SC4489,2SD2182
2SC3329	Si-NPN	AF,LN,80V,0,1A,0,4W,42MHz	7c	Tos	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2SC333	Si-NPN	=2SC322:40V	5g	Oki	BSS11,BSX19..20,2N2368..69(A)..
2SC3330	Si-NPN	GenP,60V,0,2A,0,3W,200MHz	40c	Sanyo	BC174,BC182,BC190,BC546,2SD767..
2SC3331	Si-NPN	=2SC3330:0,5W	7c	Sanyo	BC174,BC182,BC190,BC546,2SD767..
2SC3332	Si-NPN	GenP,180/160V,0,7A,0,7W,120MHz	7c	Sanyo	2SC4612
2SC3333	Si-NPN	Sw,Vid,250V,0,05A,0,6W,100MHz	7c	Tos	BF298..299,BF422,2SC3468..
2SC3334	Si-NPN	=2SC3333:0,9W	7c(9mm)	Tos	BF422(A),2SC3249,2SC3467..69
2SC3335	Si-NPN	=2SC3333:5W	14h$	Tos	BF415,BF417,BF458..459,BF469..
2SC3336	Si-NPN	Sw,Pow,500/400V,15A,100W,<0,5/2µS	18j$	Hit	BUV48(A..C),BUW13(A),2SC3520..
2SC3337	Si-NPN	VHF/UHF,20V,0,1A,0,6W,4,4GHz	7f	Hit	2SC2570(A),2SC3037,2SC3605
2SC3338	Si-NPN	UHF,15V,0,05A,4,5GHz	39b	Hit	BFQ19,BFQ193,2SC3268
2SC3339	Si-NPN	GenP,60V,0,15A,>80MHz	35d	Tos	BC846R..847R,BCV71R..72R
2SC3339-BL	Si-NPN	-	35	Tos	→2SC3339
2SC3339-GR	Si-NPN	-	35	Tos	→2SC3339
2SC3339-O	Si-NPN	-	35	Tos	→2SC3339
2SC3339-Y	Si-NPN	-	35	Tos	→2SC3339
2SC334	Si-NPN	=2SC322:60V	5g	Oki	2N4014
2SC3340	Si-NPN	GenP,120/120V,0,1A,100MHz	35d	Tos	(2SC1622A,2SC3324)
2SC3340-BL	Si-NPN	-	35	Tos	→2SC3340
2SC3340-GR	Si-NPN	-	35	Tos	→2SC3340
2SC3341	Si-NPN	GenP,35V,0,5A,300MHz	35d	Tos	BC817R,BCW65R,BCX19R,(2SC3325)
2SC3341-O	Si-NPN	-	35	Tos	→2SC3341
2SC3341-Y	Si-NPN	-	35	Tos	→2SC3341
2SC3342	Si-NPN	Sw,Pow,TV-HD,1300/500V,5A,50W	23a$	Hitachi	BU207..209A,BU508A,BU903,MJ8503..
2SC3343	Si-NPN	Sw,Pow,TV-HD,1200/500V,5A,50W	23a$	Hitachi	BU207..209A,BU508A,BU903,MJ8503..
2SC3344	Si-NPN	Sw,Pow,500/400V,8A,60W,-/<3,5µS	?15j$	Tos	MJE13006,2SC3562,2SC4106..07..
2SC3345	Si-NPN	DC-DCConv.,Lo-sat,60V,12A,40W,90MHz	17j$	Tos	2SD1212
2SC3346	Si-NPN	=2SC3345:80V,80MHz	17j$	Tos	-
2SC3347	Si-NPN	UHF-Pow,45V,2,4A,Pq=5,6W(2,2GHz)	62a&	Nec	-
2SC3348	Si-NPN	UHF-Pow,45V,3,6A,Pq=11,2W(2,2GHz)	62a&	Nec	-
2SC3349	Si-NPN	UHF-Pow,45V,0,6A,Pq=1W(2GHz)	62d*	Nec	-
2SC335	Si-NPN	=2SC322:50V,0,25W	2a$	Oki	2N4014
2SC3350	Si-NPN	UHF-Pow,45V,1,2A,Pq=3,2W(3GHz)	62a&	Nec	-
2SC3351	Si-NPN	UHF-Pow,45V,2,4A,Pq=5,4W(3GHz)	62a&	Nec	-
2SC3352	Si-NPN	Sw,Pow,800/500V,1,5A,25W,<1/4µS	17c	Mat	BUX84F..85F,2SC3794(A),2SC3978..
2SC3352A	Si-NPN	=2SC3352:900/500V,<1,2/7,2µS	17c	-	BUX85F,2SC3794A,2SC3978,2SC4304..
2SC3353	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/4µS	17c	Mat	BUT11(A)F,2SC3750,2SC3795,2SC4518
2SC3353A	Si-NPN	=2SC3353:900/500V,<1,2/7,2µS	17c	-	BUT11AF,2SC3795A,2SC4518,2SC4898
2SC3354	Si-NPN	FM/VHF,30V,0,05A,0,3W,1200MHz	40c	Mat	BF377..378,BF357,2SC2570,2SC3037,..
2SC3355	Si-NPN	UHF,20V,0,1A,0,6W,6,5GHz	7f	Nec	-
2SC3356	Si-NPN	UHF,20V,0,1A,0,2W,7GHz	35a	Nec	-
2SC3356-P	Si-NPN	-	35	Nec	→2SC3356

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2SC3356-R23	Si-NPN	-	35	Nec	→2SC3356
2SC3356-R24	Si-NPN	-	35	Nec	→2SC3356
2SC3356-R25	Si-NPN	-	35	Nec	→2SC3356
2SC3357	Si-NPN	UHF,20V,0,1A,6,5GHz	39b	Nec	2SC4988
2SC3357-RE	Si-NPN	-	39	Nec	→2SC3357
2SC3357-RF	Si-NPN	-	39	Nec	→2SC3357
2SC3357-RH	Si-NPN	-	39	Nec	→2SC3357
2SC3357-RK	Si-NPN	npn RF 1.2W fT 6.5GHz	-	Nec	-
2SC3358	Si-NPN	UHF,20V,0,1A,7GHz	25za	Nec	BFG195
2SC3359(S)	Si-NPN	GenP,80V,0,3A,0,4W,150MHz	7c,41c	Rhm	BC639,2SC4414,2SD667,2SD1226..
2SC336	Si-NPN	=2SC322:60V,0,25W	2a$	Oki	2N4014
2SC3360	Si-NPN	AF,Sw,200V,0,1A,<800/1800nS	35a	Nec	BFN24,BFN26
2SC3360-N15	Si-NPN	-	35	Nec	→2SC3360
2SC3360-N16	Si-NPN	-	35	Nec	→2SC3360
2SC3360-N17	Si-NPN	-	35	Nec	→2SC3360
2SC3361	Si-NPN	Sw,60V,0,15A,120/390nS	35a	Sanyo	BC846,BCV71..72,BSR17,2SC3392..
2SC3361-S4	Si-NPN	-	35	Sanyo	→2SC3361
2SC3361-S5	Si-NPN	-	35	Sanyo	→2SC3361
2SC3361-S6	Si-NPN	-	35	Sanyo	→2SC3361
2SC3362	Si-NPN	Sw,Pow,500/400V,1,5A,10W,<1/3µS	30j$	Hit	2SC3233,2SC3631,(BUV63,BUV93..95)
2SC3363	Si-NPN	Sw,Pow,800/500V,1A,10W,<1/4µS	30j$	Hit	(BUV94..95)
2SC3364	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,200MHz	17c	Tos	2SC3298(A,B),2SC4159,2SC4370,2SC4883A
2SC3365	Si-NPN	Sw,Pow,500/400V,10A,80W,<1/3,5µS	18j$	Hit	BUP23,2SC3042,2SC4138,2SC4434..
2SC3366	Si-NPN	AF,Sw-Pow,150/100V,5A,40W,<1/3,5µS	17j$	Hit	BD243D,MJE15030,2SD772(A,B)..
2SC3367	Si-NPN	AF,Sw-Pow,120/80V,5A,40W,300/900nS	17j$	Hit	BD243C,BDV10..12,MJE15028..
2SC3368	Si-NPN	UHF,36V,0,1A,0,5W,2,5GHz	25za	Mat	-
2SC3369	Si-NPN	UHF,36V,0,3A,1W,3GHz	25za	Mat	2SC3288,2SC3019
2SC337	Si-NPN	GenP,20V,0,02A,0,36W,100MHz	2a$	Oki	BC168,BC183,BC238,BC548,2SD767..
2SC3370	Si-NPN	AF,Sw-Pow,200V,15A,150W,30MHz	20j$	Tos	2SC2773..2774,2SC3264,2SD846
2SC3371	Si-NPN	Sw,Pow,800/500V,10A,200W,<1/4µS	23a$	Mat	BUS13(A),BUW45..46,BUX48(A..C)..
2SC3372	Si-NPN	UHF-Pow,36V,3A,Pq=8W(915MHz)	58v&	Mat	-
2SC3373	Si-NPN	UHF-Osc,30V,0,2A,0,2W,1500MHz	24b	Nec	BF363,BFW92..93
2SC3374	Si-NPN	VHF,TV-Tuner,20V,0,02A,550MHz	35a	Hit	BF599,BF799,BFS20,2SC3015..
2SC3375	Si-NPN	GenP,30V,0,8A,0,6W,120MHz	7c	Tos	BC337..338,BC635,BC637,2SD2322S,..
2SC3376	Si-NPN	Sw,Pow,900/800V,3A,60W,<-/5µS	18j$	Tos	BUW11A,2SC3152,2SC3285,2SC3550..
2SC3377	Si-NPN	GenP,40V,1A,0,5W,150MHz	7c	Rhm	BC337,BC635,BC637,2SD1225..
2SC3378	Si-NPN	AF,LN,120V,0,1A,0,2W,100MHz	41c	Tos	2SC1775A,2SC2240,2SC2389,2SC2459..
2SC3379	Si-NPN	UHF-Pow,20V,1,5A,Pq=3W(520MHz)	-	Mit	-
2SC338	Si-NPN	=2SC337:70V	2a$	Oki	BC174,BC182,BC190,BC546,2SC1890+
2SC3380	Si-NPN	Vid,300V,0,1A,80MHz	39b	Hit	BFN18,2SC3515,2SC3554
2SC3381	Si-NPN	Dual,LN,80V,0,1A,0,4W,170MHz	7-SIP/bp4	Tos	-
2SC3382	Si-NPN	=2SC3383:ra	7c	Sanyo	2SC1775(A),2SC2240,2SC2390,2SC2459,..
2SC3383	Si-NPN	GenP,60V,0,2A,0,5W,250MHz	7c	Sanyo	BC174,BC182,BC190,BC546,2SD767..
2SC3384	Si-NPN	Sw,Pow,500/400V,15A,120W,-/<2µS	23a$	Toshiba	BUV25,BUW44..46,BUX25,2SD641..
2SC3385	Si-NPN	Sw,Pow,500/400V,15A,120W,-/<1,5µS	23a$	Toshiba	BUV25,BUW44..46,BUX25,2SD641..
2SC3386	Si-NPN	AF,Sw-Pow,80/50V,3A,10W,<1/3µS	30j$	Hit	2SC3303,2SC4332,2SC4978
2SC3387	Si-NPN	Sw,Pow,1200/500V,5A,50W,<1/7µS	18j$	Hit	BU706,BU903,2SC3642,2SC4236
2SC3388	Si-NPN	Sw,Pow,1200/500V,5A,50W,<1/6µS	23a$	Hit	BU207..209,BU706,2SD1099,2SD1103
2SC3389	Si-NPN	GenP,20V,2A,0,7W,80MHz	7c	Mit	2SC3205,2SC3226,2SD787..788,2SD1246..
2SC339	Si-NPN	=2SC337:110V	2a$	Oki	2SC1775A,2SC1845,2SC2240,2SC3245..
2SC3390	Si-NPN	GenP,LN,55V,0,1A,0,3W,200MHz	41c	Hit	BF240..241,BF254..255,BF959,
2SC3391	Si-NPN	VHF,30V,0,02A,0,2W,940MHz	41c	Hit	BF377..378,BF689,BF763,2N2857..
2SC3392	Si-NPN	-	3S	Sanyo	→2SC3392
2SC3393	Si-NPN	Sw,60V,0,5A,0,3W,70/470nS	40c	Sanyo	BSV59,BSX49,2N3301..02,2N2221..22..
2SC3394	Si-NPN	GenP,55V,0,1A,0,5W,230MHz	9c	Hit	BC167,BC182,BC237,BC547,2SD767..
2SC3395	Si-NPN	-	3S	Sanyo	→2SC3395
2SC3396	Si-NPN	-	3S	Sanyo	→2SC3396
2SC3397	Si-NPN	-	3S	Sanyo	→2SC3397
2SC3398	Si-NPN	-	3S	Sanyo	→2SC3398
2SC3399	Si-NPN-Digital	R1=R2=47kΩ,50V,0,1A,250MHz	40c	Sanyo	AA1L4M,DTC144ES,RN1004,UN4213..
2SC34	Ge-NPN	AF,Sw,20V,0,25A,0,14W,6MHz	1a	Mat	AC127,ASY28..29,ASY73..75
2SC340	Si-NPN	Min,GenP,20V,0,02A,0,1W,130MHz	24c	Oki	(BC168,BC183,BC238,BC548,2SD767)
2SC3400	Si-NPN-Digital	R1=R2=22kΩ,50V,0,1A,250MHz	40c	Sanyo	AA1F4M,DTC124ES,RN1003,UN4212..
2SC3401	Si-NPN-Digital	R1=46kΩ,R2=23kΩ,50V,0,1A,250MHz	40c	Sanyo	AA1L4L,DTC144WS,RN1009,UN421E..

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2SC3402	Si-NPN-Digital	R1=R2=10kΩ, 50V, 0,1A, 250MHz	40c	Sanyo	AA1A4M, DTC114ES, RN1002, UN4211..
2SC3403	Si-NPN	Sw, Pow, 500/400V, 2A, 25W, <1/4μS	30j$	Mat	2SC4219, 2SC4597, 2SC4754
2SC3404	Si-NPN	VHF-Dr/Out, 20V, 1A, Pq=1,7W(175MHz)	-	Mit	-
2SC3405	Si-NPN	Sw, Pow, 900/800V, 0,8A, 20W, <1/5μS	30j$	Tos	2SC3489, (BUV95, BUX85, 2SC3149,..)
2SC3406	Si-NPN	UHF-Pow, 36V, 3A, Pq=8W(915MHz)	-	Mat	-
2SC3407	Si-NPN	UHF-Pow, 36V, 2A, Pq=3,5W(915MHz)	-	Mat	-
2SC3408	Si-NPN	AF/Vid, 300/300V, 0,1A, 10W, 80MHz	30j$	Mat	2SC2870, 2SC2924, 2SC3805, 2SC4019..
2SC3409	Si-NPN	Sw, Pow, 900/800V, 2A, 80W, <1/4,8μS	18j$	Sak	2SC3152, 2SC3376, 2SC3533, 2SC3550..
2SC341	Si-NPN	=2SC340: 70V	24c	Oki	(BC174, BC182, BC546, 2SC1890,..)
2SC3410	Si-NPN	UHF-Pow, 35V, 2A, Pq=7,2W(500MHz)	55s	Nec	-
2SC3411	Si-NPN	Sw, Pow, 800/400V, 10A, 50W, <1/4,5μS	23a$	Hit	BUS12(A), BUW26, BUW35..36, 2SC3049..
2SC3412	Si-NPN	Sw, Pow, TV-HD, 1200/500V, 8A, 50W, <1/4,5μS	23a$	Hit, Tho	BU137A, MJ8504..05, 2SC3215, 2SC4237..
2SC3413	Si-NPN	GenP, 40V, 0,1A, 0,3W, 200MHz	41c	Hit	BC167, BC182, BC237, BC547, 2SD767..
2SC3414	Si-NPN	=2SC3413: 0,4W	9c	Hit	→2SC3413
2SC3415(S)	Si-NPN	=2SC3269: 0,5W, S: 0,3W	7c, 41c	Rhm	BF299, RF393, BF420A, 2SC4218..
2SC3416	Si-NPN	Vid, Hi-def, 200/200V, 0,1A, 5W, 70MHz	14h$	Sanyo	2SC3502..03, 2SC3600..01, 2SD2492..
2SC3417	Si-NPN	=2SC3416: 300/300V	14h$	Sanyo	2SC3503
2SC3418	Si-NPN	=2SC3416: 400V, 100MHz	14h$	Sanyo	(BF850)
2SC3419	Si-NPN	Lo-sat, 40V, 0,8A, 5W, 100MHz	14b	Tos	2SD1684, (BD135, BD226, BD375)
2SC342	Si-NPN	=2SC340: 110V	24c	Oki	(2SC1775A, 2SC1845, 2SC2240, 2SC3245,..)
2SC3420	Si-NPN	Lo-sat, 50V, 5A, 10W, 100MHz	14b	Tos	2SD1685, (2SC2270, 2SD826)
2SC3421	Si-NPN	AF/HF/Sw-Pow, 120/120V, 1A, 10W, 120MHz	14b	Tos	2SC3621, 2SD1684
2SC3421-O	Si-NPN	120V, 1A, 1.5W	-		-
2SC3421-Y	Si-NPN	120V, 1A, 10W, 120MHz	-		-
2SC3422	Si-NPN	AF/HF/Sw-Pow, 40V, 3A, 10W, 100MHz	14b	Tos	2SD1683, 2SD1685, (BD785, MJE240..242)
2SC3422Y	Si-NPN	40V, 3A, 10W, 100MHz	-		-
2SC3423	Si-NPN	AF-Pow, 150/150V, 0,05A, SW, 200MHz	14b	Tos	2SC3787..88, 2SC3956, (BF415, BF469..)
2SC3424	Si-NPN	Sw, Vid-Pow, 250/250V, 0,05A, 80MHz	14b	Tos	2SC3271, 2SC3789..90, (BF415, BF469..)
2SC3425	Si-NPN	Sw, Pow, 500/400V, 0,8A, 10W, -/<4μS	14b	Tos	(BD410, 2SC3051)
2SC3426	Si-NPN	GenP, Lo-sat, 15V, 0,8A, 120MHz	35a	Toshiba	BCW65..66, 2SC3265
2SC3426-BL	Si-NPN	-	35	Tos	→2SC3426
2SC3426-GR	Si-NPN	-	35	Tos	→2SC3426
2SC3426-Y	Si-NPN	-	35	Tos	→2SC3426
2SC3427	Si-NPN	AF, Sw-Pow, 50V, 7A, 50W, <200/2300nS	17j$	Shi	BD543A, BD797, BD805, 2SD1442A
2SC3428	Si-NPN	AF, Sw-Pow, 60V, 10A, 50W, <200/2300nS	17j$	Shi	BD707, BD743A, BD807, 2SD1443A
2SC3429	Si-NPN	UHF, 17V, 0,07A, 5GHz	35a	Tos	2SC3161, 2SC3774
2SC343	Si-NPN	HF/Sw, 35V, 0,5A, 0,6W, 430MHz	2a$	Oki	BSV69, 2N3722..25, 2SC1072, 2SC1385..
2SC3430	Si-NPN	Sw, Pow, 500/400V, 2A, 20W, <0,5/1,8μS	15j$	Nec	BUX84..85, 2SC2333, 2SC2534, 2SC2738,..
2SC3431	Si-NPN	Sw, Pow, 500/400V, 5A, 40W, <0,5/1,8μS	15j$	Nec	MJE13070, 2SC2535, 2SC2827, 2SC3830..
2SC3432	Si-NPN	Sw, Pow, 500/400V, 7A, 60W, <0,5/1,8μS	15j$	Nec	MJE13006, 2SC3039, 2SC3170, 2SC4106..
2SC3433	Si-NPN	Sw, Pow, 500/400V, 10A, 60W, <0,5/1,8μS	15j$	Nec	MJE13008, 2SC3562, 2SC4107, 2SC4164..
2SC3434	Si-NPN	Sw, Pow, 500/400V, 10A, 100W, <0,5/1,8μS	16j$	Nec	BUP23, 2SC2828, 2SC3042, 2SC4138..
2SC3435	Si-NPN	Sw, Pow, 500/400V, 15A, 120W, <0,5/1,8μS	16j$	Nec	BUP23, 2SC3520, 2SC4139..40, 2SC4434,..
2SC3436	Si-NPN	Sw, Pow, 500/500V, 20A, 200W, <1/1,7μS	20j$	Nec	-
2SC3437	Si-NPN	HF/Sw, 40V, 0,2A, 70/45nS	35a	Toshiba	BSR17, 2SC3392
2SC3437-O	Si-NPN	-	35	Tos	→2SC3437
2SC3437-R	Si-NPN	-	35	Tos	→2SC3437
2SC3437-Y	Si-NPN	-	35	Tos	→2SC3437
2SC3438	Si-NPN	GenP, 100V, 0,5A, 130MHz	39b	Mit	2SC2881, 2SD968(A), 2SD1006..1007
2SC3438-C	Si-NPN	-	39	Mit	→2SC3438
2SC3438-D	Si-NPN	-	39	Mit	→2SC3438
2SC3438-E	Si-NPN	-	39	Mit	→2SC3438
2SC3439	Si-NPN	Lo-sat, 30V, 1,5A, 130MHz, B>400	39b	Mit	(2SC3727)
2SC3439-G	Si-NPN	-	39	Mit	→2SC3439
2SC3439-H	Si-NPN	-	39	Mit	→2SC3439
2SC3439-J	Si-NPN	-	39	Mit	→2SC3439
2SC344	Si-NPN	=2SC343: 60V	2a$	Oki	BSV77, 2N3722..23, 2SC1072, 2SC1385..
2SC3440	Si-NPN	GenP, 25V, 0,7A, 180MHz	35a	Mitsubishi	BCW65..66, 2SC3265
2SC3440-E	Si-NPN	-	35	Mit	→2SC3440
2SC3440-F	Si-NPN	-	35	Mit	→2SC3440
2SC3440-G	Si-NPN	-	35	Mit	→2SC3440
2SC3441	Si-NPN	GenP, 55V, 0,4A, 150MHz	35a	Mitsubishi	BCW65..66, BCX41, 2SD1782
2SC3441-D	Si-NPN	-	35	Mit	→2SC3441
2SC3441-E	Si-NPN	-	35	Mit	→2SC3441

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2SC3441-F	Si-NPN	-	35	Mit	→2SC3441
2SC3442	Si-NPN	GenP,50V,0,1A,0,3W,100MHz	41c	Mit	BC167,BC182,BC237,BC547,2SD767..
2SC3443	Si-NPN	Lo-sat,20V,2A,80MHz	39b	Mit	2SC2982,2SC3439,2SD1621,2SD1766..
2SC3443-E	Si-NPN	-	39	Mit	→2SC3443
2SC3443-F	Si-NPN	-	39	Mit	→2SC3443
2SC3443-G	Si-NPN	-	39	Mit	→2SC3443
2SC3444	Si-NPN	Lo-sat,60V,1A,80MHz	39b	Mit	2SC4409,2SD1615,2SD1622..1623
2SC3444-C	Si-NPN	-	39	Mit	→2SC3444
2SC3444-D	Si-NPN	-	39	Mit	→2SC3444
2SC3444-E	Si-NPN	-	39	Mit	→2SC3444
2SC3445	Si-NPN	UHF,15V,0,08A,7GHz	35a	Tos	BFR193,2SC3356
2SC3446	Si-NPN	Sw,Pow,800/500V,3A,50W,<0,5/3,3µS	17j$	Sanyo	BUT11(A),BUV46(A),2SC3047,2SC3087..
2SC3447	Si-NPN	Sw,Pow,800/500V,5A,50W,<0,5/3,3µS	17j$	Sanyo	BUT11(A),BUV46(A),2SC3087,2SC3353..
2SC3448	Si-NPN	Sw,Pow,800/500V,4A,60W,<0,5/3,3µS	18j$	Sanyo	BUW11(A),BUW131(A),2SC3088,2SC3796+
2SC3449	Si-NPN	Sw,Pow,800/500V,7A,80W,<0,5/3,3µS	18j$	Sanyo	BU426(A),BU926,2SC3089,2SC3536..
2SC345	Si-NPN	=2SC343:80V	2a$	Oki	BSV95,2N3722..23,2N3725,2N3735
2SC3450	Si-NPN	Sw,Pow,800/500V,10A,90W,<0,5/3,3µS	18j$	Sanyo	BUV47(A),BUW12(A),2SC3090,2SC3637..
2SC3451	Si-NPN	Sw,Pow,800/500V,15A,100W,<0,5/3,3µS	18j$	Sanyo	BUV48(A..C),BUW13(A),2SC3552..
2SC3452	Si-NPN	Sw,Pow,800/500V,7A,70W,<0,5/3,3µS	23a$	Sanyo	BU326(A),BU426(A),BUX47(A)..
2SC3453	Si-NPN	Sw,Pow,800/500V,10A,100W,<0,5/3,3µS	23a$	Sanyo	BUS12(A),BUW26,BUW35..35,2SC3049..
2SC3454	Si-NPN	Sw,Pow,800/500V,15A,120W,<0,5/3,3µS	23a$	Sanyo	BUS13(A),BUW45..46,BUX48(A..C)..
2SC3455	Si-NPN	Sw,Pow,800/500V,25A,160W,<0,5/3,3µS	23a$	Sanyo	BUS14(A),BUS98(A),2SC3988
2SC3456	Si-NPN	Sw,Pow,1100/800V,1,5A,40W,<0,5/3,3µS	17j$	Sanyo	MJE8500..8501,2SC3178,2SC4230
2SC3457	Si-NPN	Sw,Pow,1100/800V,3A,50W,<0,5/3,3µS	17j$	Sanyo	MJE8502..8503,2SC3050
2SC3458	Si-NPN	Sw,Pow,1100/800V,3A,80W,<0,5/3,3µS	18j$	Sanyo	2SC3387,2SC3642,2SC4236
2SC3459	Si-NPN	Sw,Pow,1100/800V,4,5A,90W,<0,5/3,3µS	18j$	Sanyo	2SC3387,2SC3642,2SC4236
2SC346	Si-NPN	HF/Sw,45V,0,7A,0,6W,<80/70nS	2a$	Oki	BSV69,2N3722..25,2SC1072,2SC1385..
2SC3460	Si-NPN	Sw,Pow,1100/800V,6A,100W,<0,5/3,3µS	18j$	Sanyo	BU902..903,BUV89,2SC3643,2SC3461,..
2SC3462	Si-NPN	Sw,Pow,1100/800V,4,5A,100W,<0,5/3,3µS	23a$	Sanyo	BU546,MJ8502..03,2SC3343,2SC4236,..
2SC3463	Si-NPN	Sw,Pow,1100/800V,6A,120W,<0,5/3,3µS	23a$	Sanyo	BU546,MJ8502..8503,3SC3343..3344..
2SC3464	Si-NPN	Sw,Pow,1100/800V,8A,130W,<0,5/3,3µS	23a$	Sanyo	BU536,MJ8504..8505,2SC3412..
2SC3465	Si-NPN	Sw,Pow,1100/800V,12A,160W,<0,5/3,3µS	23a$	Sanyo	BUX48B,C,2SC3552,2SC3644
2SC3469	Si-NPN	=2SC3467:400/400V	7c(9mm)	Sanyo	(2SC4166,2SC2267,2SD1385)
2SC347	Si-NPN	=2SC346:60V	2a$	Oki	BSV77,2N3722..23,2SC1072,2SC1385..
2SC3470	Si-NPN	GenP,55V,0,1A,0,3W,230MHz	41c	Hit	BC237,BC547,BF240..41,BF254..55..
2SC3471	Si-NPN	GenP,60V,0,2A,0,4W,250MHz	7b	Hit	BC174,BC182,BC190,BC546,2SD767..
2SC3472	Si-NPN-Darl	Sw,Pow,900/650V,3A,50W,B=20,<1/5,5µS	18j$	Fjd	BUT50P,2SC3030,2SC3032
2SC3473	Si-NPN	AF,Sw-Pow,50V,4A,40W,50MHz	17j$	Hit	2SC2562,2SC3253,(BD243A,BD535,..)
2SC3474	Si-NPN	Hi-beta,Lo-sat,80V,2A,85MHz,B>500	30j$	Tos	-
2SC3475	Si-NPN	AF,Sw-Pow,Lo-sat,100V,4A,20W,20MHz	17c	Tos	2SC3540,2SD1411
2SC3476	Si-NPN	UHF-Pow,35V,1,5A,Pq=3,5W(520MHz)	-	Mit	-
2SC3477	Si-NPN	UHF,15V,0,03A,0,35W,4,5GHz	25za	Mat	BFQ71..72,2SC1119,2SC1336
2SC3478(A)	Si-NPN	Sw,Vid,200V,0,1A,0,75W,160MHz	7c	Nec	BF298..299,BF422,2SC3467..3468..
2SC3479	Si-NPN+Diode	TV-HD,Hi-def,1500/800V,2,5A,80W	18j$	Sanyo	(BU705D,2SD1290..91,2SD1728,2SD1876)
2SC348	Si-NPN	=2SC346:60V	2a$	Oki	BSV77,2N3722..23,2SC1072,2SC1385..
2SC3480	Si-NPN+Diode	=2SC3479:3,5A	18j$	Sanyo	(BU706D,2SD1729,2SD1877)
2SC3481	Si-NPN+Diode	TV-HD,Hi-def,1500/800V,5A,120W	18j$	Sanyo	2SC3681,(BU2508D,2SD1730,2SD1878)
2SC3482	Si-NPN+Diode	=2SC3481:6A	18j$	Sanyo	2SC3681,(BU508D,2SD1731,2SD1879)
2SC3483	Si-NPN	TV-HD,Hi-def,1500V,2,5A,80W	18j$	Sanyo	(BU705,2SD1493..1494,..)
2SC3484	Si-NPN	=2SC3483:3,5A	18j$	Sanyo	(BU706,2SC3484,2SD1495)
2SC3485	Si-NPN	TV-HD,Hi-def,1500/800V,5A,120W	18j$	Sanyo	2SC3685,(BU2508(A),2SD1496..97)
2SC3486	Si-NPN	=2SC3485:6A	18j$	Sanyo	2SC3685..86,(BU2508(A),2SD1496..1497)
2SC3487	Si-NPN	GenP,50V,0,1A,0,3W,150MHz	7c	Tos	BC167,BC182,BC237,BC547,2SD767..
2SC3488	Si-NPN	GenP,35V,0,5A,0,3W,300MHz	41c	Tos	BC337..338,BC635,BC637,2SC3377..
2SC3489	Si-NPN	Sw,Pow,900/800V,0,8A,10W,<1/1,7µS	30j$	Hit	2SC3405,(BUV95,BUX85,2SC3149,..)
2SC349	Si-NPN	=2SC346:90V	2a$	Oki	BSV95,2N3722..23,2N3625,2N3735
2SC3490	Si-NPN	Sw,Pow,900/800V,3A,40W,<0,5/3µS	17j$	Hit	BUT11(A),BUV46(A),2SC3148,2SC3150
2SC3491	Si-NPN	Sw,Pow,1000/400V,4A,60W,<0,75µS	17j$	Hit	BUT11A,BUV46A,2SC3050,2SC3457..
2SC3492	Si-NPN	AF,Sw-Pow,50V,4A,40W,50MHz	17j$	Hit	2SC2562,2SC3253,(BD243,BD535,..)
2SC3493	Si-NPN	VHF,TV-Tuner,15V,20mA,>700MHz	35a	Hit	BF599,BF799,BFS17,BFS20,2SC3130+
2SC3494	Si-NPN	FM-HF/AF,30V,0,1A,0,3W	41c	Hit	BF240..41,BF254..55,BF594..595..
2SC3495	Si-NPN	Hi-beta,Hi-Ueb,120V,0,05A,B=1000	7c	Sanyo	2SC3071
2SC3496(A)	Si-NPN	Sw,Pow,900/800V,1A,30W,<1/4µS	30j$	Mat	2SC4223,2SC4601,(BUV95,BUX85,..)
2SC3497	Si-NPN	Sw,Pow,500/400V,6A,30W,-/<1,8µS	17c	Tos	BUF306F,2SC3870,2SC4130,2SC4161..

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2SC3498	Si-NPN	Sw,Pow,500/400V,30A,150W,-/<3µS	77j$	Tos	-
2SC3499	Si-NPN	Sw,Pow,500/450V,30A,150W	77j$	Tos	-
2SC35	Ge-NPN	AF,Sw,20V,0,4A,0,14W,12MHz	1a	Mat	AC127,ASY73..75
2SC350	Si-NPN	GenP,LN,30V,0,1A,0,2W,180MHz	2a	Hit	BC169,BC184,BC239,BC549,2SC2675+
2SC3500(1)	Si-NPN	UHF-Pow,50V,4A,Pq=4,8W(860MHz)	61r	Nec	-
2SC3501	Si-NPN	VHF-Mix/Osc,TV-Tuner,20V,0,05A,3,5GHz	24b	Hit	BFT65
2SC3502	Si-NPN	Vid-Pow,Hi-def,200V,0,1A,7W,150MHz	14h$	Sanyo	2SC3416..17,2SC3600..01
2SC3503	Si-NPN	=2SC3502:300/300V	14h$	Sanyo	2SC3417..18,(BF417,BF471)
2SC3504	Si-NPN	CRT,Hi-def,70V,0,05A,0,9W,500MHz	7c(9mm)	Sanyo	2SC3596
2SC3505	Si-NPN	Sw,Pow,900/700V,6A,80W,<1/6µS	18j$	Fjd	BUW11A,2SC3153,2SC3232,2SC3535..
2SC3506	Si-NPN	Sw,Pow,SMPS,1000/800V,3A,70W,<1/3µS	16c	Mat	BUW11AF,2SC4426..27,2SC4583..84
2SC3507	Si-NPN	Sw,Pow,SMPS,1000/800V,5A,80W,<1/3µS	16c	Mat	BUW11AF,2SC4427..28,2SC4584
2SC3508	Si-NPN-Darl	B2→B1-Diode,900/800V,6A,80W,B>7	16c	Mat	-
2SC3509	Si-NPN-Darl	B2→B1-Diode,900/800V,10A,100W,B>7	16c	Mat	-
2SC351	Si-NPN	HF,40V,0,02A,0,2W,600MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3510	Si-NPN	UHF,20V,0,05A,0,6W,4,5GHz	7f	Hit	2SC2570(A),2SC3037,2SC3337,2SC3512
2SC3511	Si-NPN	UHF,15V,0,05A,0,2W,6GHz	2Sza	Hit	BFG65,BFP91,BFQ66
2SC3512	Si-NPN	VHF/UHF,15V,0,1A,0,6W,6GHz	7f	Hit	2SC3355
2SC3513	Si-NPN	-	3S	Hit	→2SC3513
2SC3514	Si-NPN	AF-Pow,180/180V,0,1A,10W,200MHz	17j$	Nec	2SC3782,(BF615,BF858..859,BF757..)
2SC3515	Si-NPN	Vid,300/300V,0,1A,80MHz	39b	Tos	BFN18,2SC3380,2SC3554,2SC4189
2SC3515-O	Si-NPN	-	39	Tos	→2SC3515
2SC3515-R	Si-NPN	SI-N300V0.1Ahfe=30-90	-	Toshiba	-
2SC3515-Y	Si-NPN	-	39	Tos	→2SC3515
2SC3516	Si-NPN	Sw,Pow,1200/800V,30A,200W	?74	Org	-
2SC3517	Si-NPN	Sw,Pow,1200/800V,50A,300W	?74	Org	-
2SC3518	Si-NPN	60V,5A,10W	-		-
2SC3518(-Z)	Si-NPN	AF,Sw-Pow,60V,5A,10W,<1/3µS	30j$	Nec	2SC3074,2SC3303,2SC3592,2SD1803..
2SC3519	Si-NPN	AF,Sw-Pow,160V,15A,130W,50MHz	18j$	Sak	2SC2987A,2SC3263,2SD1047,2SD1703
2SC3519A	Si-NPN	=2SC3519:180V	18j$	-	2SC3263,2SC3907,2SC3856
2SC352(A)	Si-NPN	HF/Sw,50V,0,1A,0,75W,140MHz	2a$	Son	BSY58,2N2218..19(A),2N3299..3300..
2SC3520	Si-NPN	Sw-Reg,500/400V,18A,130W,<0,7/3,7µS	18j$	Sak	2SC3850,2SC4110,2SC4140
2SC3521	Si-NPN	Sw,40V,0,1A,<100/150nS	35a	Hitachi	BSR17,2SC3361,2SC3578
2SC3521-B	Si-NPN	-	3S	Hit	→2SC3521
2SC3521-C	Si-NPN	-	3S	Hit	→2SC3521
2SC3522	Si-NPN	Sw,Pow,500/400V,7A,40W,<1/3,5µS	17j$	old	MJE13006,2SC3039,2SC3170,2SC4106..
2SC3523	Si-NPN	AF,Sw-Pow,100V,3A,40W	17j$	old	2SC3258,(BD241C,BD937,BDV10..12,+)
2SC3524	Si-NPN	AF,Sw-Pow,150V,7A,40W,<0,5/2µS	17j$	old	BD243D,MJE15030,2SC2334,2SC4329
2SC3525	Si-NPN	Sw,Pow,500/400V,5A,100W,<1/3µS	23a$	old	BUP22,BUX45,TIP58A,2SC3083..
2SC3526	Si-NPN	110V,0.15A,7A,30W,1µS	-		-
2SC3526(H)	Si-NPN	Display-Video,110V,0,15A,1W,350MHz	7c(9mm)	Mat	(2SC3598..99,2SC3953..54)
2SC3527	Si-NPN	Sw,Pow,500/400V,15A,100W,<1/3,5µS	16c	Mat	2SC4298,2SC4424
2SC3528	Si-NPN	Sw,Pow,500/400V,20A,125W,<1/3,5µS	16c	Mat	2SC4425
2SC3529	Si-NPN	Sw,Pow,500/400V,5A,40W,<0,5/1,8µS	17j$	Nec	MJE13070,2SC2535,2SC2827,2SC3830..
2SC353(A)	Si-NPN	=2SC352:100V	2a$	Son	BSW39,2N3723
2SC3531	Si-NPN	Sw,Pow,1000/800V,3A,50W,<1/3,5µS	17j$	Nec	BUT11A,BUV46A,MJE8502..03,2SC3457,..
2SC3532	Si-NPN	Sw,Pow,1000/800V,4A,60W,<1/3,5µS	15j$	Nec	BUT11A,BUV46A,MJE8502..03,2SC3491
2SC3533	Si-NPN	Sw,Pow,1000/800V,3A,70W,<1/3,5µS	16j$	Nec	BUW11A,BUW131A,2SC3285,2SC3534..
2SC3534	Si-NPN	Sw,Pow,1000/800V,4A,80W,<1/3,5µS	16j$	Nec	BUW11A,BUW131A,2SC3285,2SC3387..
2SC3535	Si-NPN	Sw,Pow,1000/800V,6A,100W,<1/3,5µS	16j$	Nec	BUW11A,BUW131A,2SC3387,2SC3642..
2SC3536	Si-NPN	Sw,Pow,1000/800V,8A,120W,<1/3,5µS	16j$	Nec	BU902..903,BUV47A,BUW12A
2SC3537	Si-NPN	UHF-Pow,50V,3A,Pq=20W(900MHz)	61v	Nec	-
2SC3538	Si-NPN	UHF-Pow,50V,6A,Pq=40W(900MHz)	61v	Nec	-
2SC3539	Si-NPN	UHF-Pow,50V,9A,Pq=60W(900MHz)	61v	Nec	-
2SC354	Si-NPN	VHF-A/Dr,40V,1,5A,7W,180MHz	2a$	Fui	BFQ43,2N4427
2SC3540	Si-NPN	AF,Sw-Pow,Lo-sat,100V,5A,25W,120MHz	17c	Tos	2SC3691,2SC4549,2SC4596
2SC3541	Si-NPN	UHF-Pow,35V,2A,Pq=5,6W(1300MHz)	61v	Nec	-
2SC3542	Si-NPN	UHF-Pow,35V,6A,Pq=15,8W(1300MHz)	61v	Nec	-
2SC3544	Si-NPN	UHF,30V,0,05A,0,25W,2GHz	7f	Nec	BF357,2SC2498,2SC2570(A),2SC3037..
2SC3545	Si-NPN	UHF,30V,0,05A,0,25W,2GHz	35a	Nec	BFR53,BFT75,2SC3014
2SC3545-K/R	Si-NPN	-	35	Nec	→2SC3545
2SC3545-L/Q	Si-NPN	-	35	Nec	→2SC3545
2SC3545-M/P	Si-NPN	-	35	Nec	→2SC3545
2SC3545-P	Si-NPN	npn RF fT 2GHz hfe 50-100	-	Nec	-

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2SC3545-R	Si-NPN	npn RF fT 2GHz hfe 120-250	-	Nec	-
2SC3546	Si-NPN	AF, Sw-Pow, 160/160V, 12A, 120W, 30MHz	20j$	Tos	2SC2526, 2SC2565, 2SC2766(A), 2SC2921,..
2SC3547(A,B)	Si-NPN	UHF-Osc, TV-Tuner, 20V, 0,03A, 4GHz	35a	Tos	BFQ29, BFR93, BFT75
2SC3547-B	Si-NPN	-	35	Tos	→2SC3547B
2SC3548	Si-NPN	UHF, 20V, 0,03A, 4GHz	25za	Tos	BFQ59..60, BFQ70..71, 2SC2143..
2SC3549	Si-NPN	Sw, Pow, 900/800V, 3A, 40W, <1/4,8µS	17j$	Fjd	BUT11A, BUV46, 2SC3148, 2SC3490..
2SC355	Si-NPN	VHF-Pow, 75V, 2,5A, Pq=3W(150MHz)	49a	Fui	BLY35, BLY60, 2N3632
2SC3550	Si-NPN	Sw, Pow, 900/800V, 3A, 80W, <1/4,8µS	18j$	Fjd	BUW11A, BUW131A, 2SC3152, 2SC3376..
2SC3551	Si-NPN	Sw, Pow, 900/800V, 5A, 80W, <1/4,8µS	18j$	Fjd	BUW11A, BUW131A, 2SC3153, 2SC3232..
2SC3552	Si-NPN	Sw, Pow, 1100/800V, 12A, 150W, 15MHz	18j$	Sanyo	BUV48B,C, BUW13A, 2SC3644
2SC3553	Si-NPN	GenP, 35V, 0,5A, 0,3W, 120MHz	41c	Hit	BC337..338, BC635, BC637, 2SC3377..
2SC3554	Si-NPN	Sw, Vid, 300/300V, 0,2A, 50MHz	39b	Nec	BFN18, 2SC3515, 2SC3380
2SC3554-SK	Si-NPN	-	39	Nec	→2SC3554
2SC3554-SL	Si-NPN	-	39	Nec	→2SC3554
2SC3554-SM	Si-NPN	-	39	Nec	→2SC3554
2SC3555	Si-NPN	Sw, Pow, 900/800V, 0,5A, 20W, <1/5µS	30j$	Hit	2SC3405, 2SC3489, 2SD1945, (BUX87,..)
2SC3556	Si-NPN	AF, Sw-Pow, 80V, 4A, 40W, <0,5/2,5µS	17j$	Hit	BD243B, BD537, BD539B, BDV10..12..
2SC3557	Si-NPN	AF, Sw-Pow, 80V, 4A, 40W, <0,5/2µS	17j$	Hit	BD243B, BD537, BD539B, BDV10..12..
2SC3558	Si-NPN	AF, Sw-Pow, 100/60V, 4A, 40W, <0,5/3µS	17j$	Tos	BD243C, BD539C, BD953, BDV10..12..
2SC3559	Si-NPN	Sw, Pow, 900/800V, 3A, 30W, <1/5µS	17c	Tos	BUT11AF, 2SC3752, 2SC4304, 2SC4234..
2SC356	Si-NPN	Fast-Sw, 30V, 0,2A, 0,3W, <20/40nS	2a$	Nec	BSS11..12, BSW38, 2N2368..69(A)..
2SC3560	Si-NPN	Sw, Pow, 500/400V, 2A, 20W, -/<1,9µS	17c	Tos	BUX84F..85F, 2SC3309, 2SC3569, 2SC4421..
2SC3561	Si-NPN	Sw, Pow, 500/450V, 2A, 20W	17c	Tos	BUX84F..85F, 2SC3309, 2SC3569, 2SC4421..
2SC3562	Si-NPN	Sw, Pow, 500/400V, 10A, 40W, -/1,8µS	17c	Tos	2SC3572, 2SC3575, 2SC4162, 2SD1795..
2SC3563	Si-NPN	=2SC3562: 500/450V	17c	Tos	2SC3572, 2SC3575, 2SC4162, 2SD1795..
2SC3564	Si-NPN	AF, Sw-Pow, 120/120V, 1,5A, 200MHz	17c	Nec	2SC3364, (2SC3298(A,B), 2SC4159)
2SC3565	Si-NPN	Vid/Sw, Pow, 300/300V, 0,2A, 15W, 80MHz	17c	Nec	2SC4075, (2SC1505..07, 2SC1755..57,..)
2SC3566	Si-NPN	Hi-Ueb, 150/60V, 5A, 25W, <0,5/3µS	17c	Nec	(2SC3568, 2SC3696, 2SC4153, 2SC4334..35)
2SC3567	Si-NPN	AF, Sw-Pow, 150/100V, 3A, 15W, <0,5/2µS	17c	Nec	BDT31DF, 2SC3695
2SC3568	Si-NPN	AF, Sw-Pow, 150/100V, 10A, 30W, <0,5/2µS	17c	Nec	2SC3698, 2SC4336, (BD743E)
2SC3569	Si-NPN	Sw, Pow, 500/400V, 2A, 15W, <1/3,5µS	17c	Nec	BUX84F..85F, 2SC3560..61, 2SC4421..
2SC357..359	Si-NPN	-		Nec	-
2SC3570	Si-NPN	Sw, Pow, 500/400V, 5A, 25W, <1/2,7µS	17c	Nec	BUT11(A)F, 2SC3310, 2SC4054, 2SC4371,..
2SC3571	Si-NPN	Sw, Pow, 500/400V, 7A, 30W, <1/3,5µS	17c	Nec	2SC3890, 2SC4056, 2SC4130, 2SC4161..
2SC3572	Si-NPN	Sw, Pow, 500/400V, 10A, 30W, <1/3,2µS	17c	Nec	2SC3310, 2SC3562, 2SC4162, 2SD1795
2SC3573	Si-NPN	Sw, Pow, 500/400V, 5A, 30W, <0,5/1,8µS	17c	Nec	BUT11(A)F, 2SC3310, 2SC4054, 2SC4371,..
2SC3574	Si-NPN	Sw, Pow, 500/400V, 7A, 30W, <0,5/1,8µS	17c	Nec	2SC3890, 2SC4056, 2SC4130, 2SC4161..
2SC3575	Si-NPN	Sw, Pow, 500/400V, 10A, 30W, <0,5/1,8µS	17c	Nec	2SC3310, 2SC3562, 2SC4162, 2SD1795
2SC3576	Si-NPN	Hi-beta, Hi-Ueb, Lo-sat, 30V, 0,3A, B=1500	40c	Sanyo	2SC3068, 2SC3836
2SC3577	Si-NPN	Sw, Pow, 850/650V, 5A, 80W, <1/3µS	16c	Mat	BUW11(A)F, 2SC4300, 2SC4457
2SC3578	Si-NPN	Sw, 40V, 0,1A, <40/70nS	35a	Hitachi	2SC3757
2SC3579	Si-NPN	Sw, Pow, 800/800V, 6A, 50W, <0,5/3,7µS	17j$	Shi	BUT11A, BUV46A, 2SC3050, 2SC3047..
2SC3580	Si-NPN	AF-Dr/Out, 25V, 0,7A, 0,9W, 180MHz	7c(9mm)	Mit	BC337..338, 2SC2236, 2SD863, 2SD1331,..
2SC3581	Si-NPN	AF-Dr/Out, 55V, 0,4A, 0,9W, 150MHz	7c(9mm)	Mit	BC637, 2SC3939, 2SD863, 2SD1937..
2SC3582	Si-NPN	UHF, 20V, 0,065A, 0,6W, 8GHz	7f	Nec	-
2SC3583	Si-NPN	UHF, 20V, 0,065A, 9GHz	35a	Nec	BFR520
2SC3583-R33	Si-NPN	-	35	Nec	→2SC3583
2SC3583-R34	Si-NPN	-	35	Nec	→2SC3583
2SC3583-R35	Si-NPN	-	35	Nec	→2SC3583
2SC3584	Si-NPN	UHF, 20V, 0,065A, 0,2W, 9GHz	25za	Nec	-
2SC3585	Si-NPN	UHF, 20V, 0,035A, 10GHz	35a	Nec	2SC5089
2SC3585-P	Si-NPN	npn RF fT 10GHz @ 10mA	-	Nec	-
2SC3585-Q	Si-NPN	npn RF fT 10GHz hfe 50-100	-	Nec	-
2SC3585-R43	Si-NPN	-	35	Nec	→2SC3585
2SC3585-R44	Si-NPN	-	35	Nec	→2SC3585
2SC3585-R45	Si-NPN	-	35	Nec	→2SC3585
2SC3585-S	Si-NPN	npn RF fT 10GHz hfe 125-250	-	Nec	-
2SC3586	Si-NPN	UHF, 20V, 0,035A, 0,25W, 10GHz	25za	Nec	BFQ645
2SC3587	Si-NPN	UHF, 20V, 0,03SA, 0,58W, 10GHz	51s	Nec	BFQ645
2SC3588(-Z)	Si-NPN	Sw, Pow, 500/400V, 0,5A, 10W, <1/3,5µS	30j$	Nec	2SC3129, 2SC3075, (BUX84..85, 2SC2899)
2SC3589	Si-NPN	HD, Hi-def, Lo-sat, 250/100V, 7A, 40W	17j$	Sanyo	(BU406..408, 2SC3173, 2SC3175)
2SC3590	Si-NPN	HD, Hi-def, Lo-sat, 330/150V, 7A, 50W	17j$	Sanyo	(BU406..408, 2SC3173, 2SC3175)
2SC3591	Si-NPN	=2SC3590: 400/200V	17j$	Sanyo	(BU406, BU408, 2SC3175)
2SC3592	Si-NPN	AF, Sw-Pow, 60V, 5A, 10W, <1/3,5µS	30j$	Nec	2SC3074, 2SC3518, 2SD1803, 2SD1805..

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2SC3593	Si-NPN	Sw,Pow,850V,25A,150W,<3/2,5µS	23a$	Mat	BUS14(A),BUS98(A)
2SC3594	Si-NPN	Sw,Pow,1400/650V,8A,50W,<500/5,5µS	23a$	Hit	BU508A,BUV71,MJ8505,2SC4284..85
2SC3595	Si-NPN	Vid-Out,Hi-def,30V,0,5A,5W,2GHz	14h$	Sanyo	-
2SC3596	Si-NPN	Vid-Out,Hi-def,80V,0,3A,8W,700MHz	14h$	Sanyo	2SC3599,2SC3951
2SC3597	Si-NPN	Vid-Out,Hi-def,80V,0,5A,10W,800MHz	14h$	Sanyo	2SC3952
2SC3598	Si-NPN	Vid-Out,Hi-def,120V,0,2A,8W,500MHz	14h$	Sanyo	2SC3599,2SC3953..54
2SC3599	Si-NPN	Vid-Out,Hi-def,120V,0,3A,8W,500MHz	14h$	Sanyo	2SC3954
2SC36	Ge-NPN	AF,Sw,20V,0,4A,0,14W,20MHz	1a	Mat	AC127,ASY73..75
2SC360	Si-NPN	GenP,30V,0,1A,0,25W,150MHz	2a$	Tos	BC168,BC183,BC238,BC548,2SD767..
2SC3600	Si-NPN	Vid-Out,Hi-def,200V,0,1A,7W,400MHz	14h$	Sanyo	2SC3601,2SC3955
2SC3601	Si-NPN	Vid-Out,Hi-def,200V,0,15A,7W,400MHz	14h$	Sanyo	2SC3956
2SC3602	Si-NPN	UHF,25V,0,02A,0,2W,1100MHz	25u	Tos	2SC2464,2SC2466,2SC2144,2SC2360..
2SC3603	Si-NPN	UHF,20V,0,1A,0,58W,7GHz	51s	Nec	BFQ196,2SC3358
2SC3604	Si-NPN	UHF,20V,0,065A,0,58W,8GHz	51s	Nec	BFQ82,2SC3358
2SC3605	Si-NPN	UHF,20V,0,08A,6,5GHz	7f	Tos	2SC2570(A),2SC3037,2SC3512,2SC3355
2SC3606	Si-NPN	-	3S	Tos	→2SC3606
2SC3607	Si-NPN	-	39	Tos	→2SC3607
2SC3608	Si-NPN	-	2S	Tos	→2SC3608
2SC3609	Si-NPN	-	44	Tos	→2SC3609
2SC361	Si-NPN	HF,25V,40mA,150MHz,B=80	7c	Tos	BF240..241,BF254..255,BFS94..595,..
2SC3610	Si-NPN	Vid-Pow,i-res,110V,0,15A,10W,300MHz	17j$	Mat	2SC3781
2SC3611	Si-NPN	=2SC3610:4W	14h$	Mat	2SC3598..99
2SC3612	Si-NPN	Vid-Out,Hi-res,180V,0,3A,20W,400MHz	17j$	Tos	-
2SC3613	Si-NPN	Vid-Dr,Hi-res,20V,0,5A,5W,3500MHz	14b	Tos	-
2SC3614	Si-NPN	VHF/UHF,20V,0,1A	39b	Hit	2SC3357
2SC3615	Si-NPN	Hi-beta,Hi-Ueb,50V,0,3A,B>800,220MHz	7c	Nec	2SC3836,2SD1915
2SC3616	Si-NPN	Hi-beta,Hi-Ueb,25V,0,7A,B>800,250MHz	7c	Nec	2SC3070,2SC4204,2SD1582
2SC3617	Si-NPN	=2SC3615:SMD	39b	Nec	-
2SC3617-TK	Si-NPN	-	39	Nec	→2SC3617
2SC3617-TL	Si-NPN	-	39	Nec	→2SC3617
2SC3617-TM	Si-NPN	-	39	Nec	→2SC3617
2SC3618	Si-NPN	=2SC3616:SMD	39b	Tos	2SC3650
2SC3618-UK	Si-NPN	-	39	Nec	→2SC3618
2SC3618-UL	Si-NPN	-	39	Nec	→2SC3618
2SC3618-UM	Si-NPN	-	39	Nec	→2SC3618
2SC3619	Si-NPN	Sw,Vid-Pow,300/300V,0,1A,>50MHz	14b	Tos	2SC3271,2SC3789..90,2SC4828
2SC362	Si-NPN	=2SC361:a=140	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3620	Si-NPN	Vid-Pow,300/300V,0,1A,>50MHz	14b	Tos	2SC3271,2SC3789..90,2SC4828
2SC3621	Si-NPN	CTV-HD,AF-Pamp,150V,1,5A,10W,100MHz	14b	Tos	2SC3902,(2SC3117,2SD669,2SD781)
2SC3622(A)	Si-NPN	Hi-beta,Hi-Ueb,60V,0,15A,B=1800	7c	Nec	2SC3069,2SC3836
2SC3623	Si-NPN	60V,0.15A,0.25W,B=1000	-		-
2SC3623(A)	Si-NPN	=2SC3622:	40c	Nec	2SC3069,2SC3836
2SC3624(A)	Si-NPN	=2SC3622:SMD	35a	Nec	2SC3689
2SC3624A-L15	Si-NPN	-	3S	Nec	→2SC3624A
2SC3624A-L16	Si-NPN	-	3S	Nec	→2SC3624A
2SC3624-L17	Si-NPN	-	3S	Nec	→2SC3624
2SC3624-L18	Si-NPN	-	3S	Nec	→2SC3624
2SC3625	Si-NPN	Sw,Pow,500/400V,8A,60W,<1/3,5µS	17j$	Tos	MJE13006,2SC3170,2SC3562,2SC4107..
2SC3626	Si-NPN	=2SC3625:40W	17c	Tos	2SC3574..75,2SC3890,2SC4130,2SC4161..
2SC3627	Si-NPN	Sw-Reg,250/200V,10A,40W,<1/3,5µS	17c	Tos	2SC3572,2SC3575,2SC4162,2SD1795..
2SC3628	Si-NPN	VHF-Pow,35V,2A,Pq=6,5W(175MHz)	58s	Mit	-
2SC3629	Si-NPN	UHF-Pow,20V,1A,Pq=1,5W(520MHz)	58s	Mit	-
2SC363	Si-NPN	=2SC361:a=250	7c	Tos	BF240..241,BF254..255,BFS94..595,..
2SC3630	Si-NPN	UHF-Pow,35V,1A,Pq=3,3W(520MHz)	58s	Mit	-
2SC3631(-Z)	Si-NPN	Sw,Pow,500/400V,2A,10W,50MHz	30j$	Nec	2SC3233,(BUV93..94)
2SC3632	Si-NPN	600V,1A,10W,30MHz	-		-
2SC3632(-Z)	Si-NPN	Sw,Pow,600/600V,1A,10W,30MHz	30j$	Nec	2SC3363
2SC3633	Si-NPN+Diode	=2SC3636:integr.Damper-Diode	18j$	Sanyo	2SC3639
2SC3634	Si-NPN+Diode	=2SC3637:integr.Damper-Diode	18j$	Sanyo	2SC3640
2SC3635	Si-NPN+Diode	=2SC3638:integr.Damper-Diode	18j$	Sanyo	2SC3641
2SC3636	Si-NPN	HD,Hi-def,900/500V,7A,80W	18j$	Sanyo	2SC3643
2SC3637	Si-NPN	HD,Hi-def,900/500V,10A,90W	18j$	Sanyo	2SC3644
2SC3638	Si-NPN	HD,Hi-def,900/500V,15A,100W	18j$	Sanyo	-
2SC3639	Si-NPN+Diode	=2SC3642:integr.Damper-Diode	18j$	Sanyo	-

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2SC364	Si-NPN	=2SC361:a=400	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3640	Si-NPN+Diode	=2SC3643:integr.Damper-Diode	18j$	Sanyo	-
2SC3641	Si-NPN+Diode	=2SC3644:integr.Damper-Diode	18j$	Sanyo	-
2SC3642	Si-NPN	HD,Hi-def,1200/800V,6A,100W	18j$	Sanyo	2SC3686..87
2SC3643	Si-NPN	HD,Hi-def,1200/800V,8A,140W	18j$	Sanyo	2SC3687
2SC3644	Si-NPN	HD,Hi-def,1200/800V,12A,150W	18j$	Sanyo	BU2525A
2SC3645	Si-NPN	GenP,180/160V,0,14A,150MHz	39b	Sanyo	BFN16,BFN18
2SC3646	Si-NPN	GenP,120V,1A,120MHz	39b	Sanyo	2SC3647,2SC4132,2SC4373,2SD1418..19
2SC3647	Si-NPN	GenP,120V,2A,120MHz	39b	Sanyo	2SC4132
2SC3648	Si-NPN	GenP,180V,0,7A,120MHz	39b	Sanyo	2SC3649,2SD1420..1421
2SC3649	Si-NPN	GenP,180V,1,5A,120MHz	39b	Sanyo	2SD1420..1421
2SC3650	Si-NPN	Hi-Ueb,Hi-beta,30V,1,2A,B=1500	39b	Sanyo	(2SD1950)
2SC3651	Si-NPN	Hi-Ueb,Hi-beta,120V,0,2A,B>500	39b	Sanyo	-
2SC3652	Si-NPN	HF-Pow,30V,0,3A,5W,1200MHz	14h$	Hit	-
2SC3653	Si-NPN-Digital	=2SC3399:0,4W	7c	Sanyo	→2SC3399
2SC3654	Si-NPN-Digital	=2SC3400:0,4W	7c	Sanyo	→2SC3400
2SC3655	Si-NPN-Digital	=2SC3401:0,4W	7c	Sanyo	→2SC3401
2SC3656	Si-NPN-Digital	=2SC3402:0,4W	7c	Sanyo	→2SC3402
2SC3657	Si-NPN	Sw,Pow,900/800V,4A,80W,<1/3,5µS	18j$	Tos	BUW11A,2SC3153,2SC3232,2SC3535..
2SC3658	Si-NPN+Diode	Sw,Pow,TV-HD,1500/800V,5A,50W	23a$	Hitachi	BU208D,BU508D,2SC4291,2SD1171..75..
2SC3659	Si-NPN+Diode	Sw,Pow,TV-HD,1700/800V,5A,50W	23a$	Hitachi	(BU209,2SC3026,2SD784..785)
2SC366(G,GTM)	Si-NPN	GenP,50..60V,0,4A,0,3W,120MHz	7c	Tos	BC337(A),BC637,BC639,2SD1226..
2SC3660(A)	Si-NPN	UHF-Pow,55V,24A,Pq=105W(620MHz)	-	Nec	-
2SC3661	Si-NPN	Hi-Ueb,Hi-beta,30V,0,3A,B=1500	35a	Sanyo	2SD1938
2SC3662	Si-NPN	UHF,25V,0,02A,1100MHz	44zf	Tos	-
2SC3663	Si-NPN	UHF,15V,5mA,4GHz	35a	Nec	BFQ29,BFQ81,BFR93,2SC3099
2SC3664	Si-N-Darl+Di	Sw,Pow,800/400V,20A,150W,B>80	18j$	Sanyo	-
2SC3665	Si-NPN	GenP,120/120V,0,8A,1W,120MHz	9c	Tos	2SC2235,2SC3665,2SD667,2SD1616A..
2SC3666	Si-NPN	GenP,30V,1A,1W,150MHz	9c	Tos	BC337..338,BC635,BC637,2SD1225..
2SC3667	Si-NPN	GenP,30V,1,5A,1W,120MHz	9c	Tos	MPS650..651,2SC2236,2SD1051,2SD1331..
2SC3668	Si-NPN	GenP,50V,2A,1W,100MHz	9c	Tos	MPS650..651,2SD1014,2SD1146,2SD1207..
2SC3669	Si-NPN	GenP,80V,2A,1W,100MHz	9c	Tos	MPS651,2SC3328,2SC4145,2SD1642
2SC367(G,GTM)	Si-NPN	GenP,40V,0,4A,0,3W,120MHz	7c	Tos	BC337,BC635,BC637,2SD1225..26..
2SC3670	Si-NPN	Strobo Flash,Lo-sat,30V,2A,1W,150MHz	9c	Tos	2SC4484,2SC4486,2SD1207,2SD1246..47
2SC3671	Si-NPN	Strobo Flash,50V,5A,1W,100MHz	9c	Tos	2SC4482,2SD1145,2SD1961..62,2SD2179
2SC3672	Si-NPN	Vid,300/300V,0,1A,1W,80MHz	9c	Tos	BF299,BF393,BF420A,2SC3468..
2SC3673	Si-NPN	Hi-beta,40V,2A,1W,220MHz,B=1000	9c	Tos	2SC3225,2SD1779
2SC3674	Si-NPN	UHF,15V,0,065A,0,4W,8GHz	51s	Mat	BFQ66,BFQ82,2SC3603
2SC3675	Si-NPN	Dynamic Focus,1500/900V,0,1A,10W	17j$	Sanyo	-
2SC3676	Si-NPN	Dynamic Focus,1500/900V,0,3A,20W	17j$	Sanyo	-
2SC3677	Si-NPN	AF,Sw-Pow,60V,3A,25W,170MHz,B=2000	17c	Tos	2SD1273,2SD1972,2SD2177
2SC3678	Si-NPN	Sw,Pow,900/800V,3A,80W,6MHz,<1/6µS	18j$	Sak	BUW11A,2SC3152,2SC3285,2SC3550..
2SC3679	Si-NPN	Sw,Pow,900/800V,5A,100W,6MHz,<1/6µS	18j$	Sak	BUW11A,2SC3153,2SC3387,2SC3466..
2SC368	Si-NPN	GenP,LN,25V,0,1A,0,25W,150MHz	2a$	Tos	BC169,BC184,BC239,BC549,2SC2675+
2SC3680	Si-NPN	Sw,Pow,900/800V,7A,120W,6MHz,<1/6µS	18j$	Sak	BUV47A,BUW12A,2SC3466,2SC3636..
2SC3681	Si-NPN+Diode	=2SC3685:integr.Damper-Diode	18j$	Sanyo	2SC3482,2SC4292,(BU508D,BU706D)
2SC3682	Si-NPN+Diode	=2SC3686:integr.Damper-Diode	18j$	Sanyo	(BU508D,BU2808D)
2SC3683	Si-NPN+Diode	=2SC3687:integr.Damper-Diode	18j$	Sanyo	BU2520D
2SC3684	Si-NPN+Diode	=2SC3688:integr.Damper-Diode	18j$	Sanyo	BU2520D
2SC3685	Si-NPN	TV-HD,Hi-def,1500/800V,6A,120W	18j$	Sanyo	2SC3486,(BU508A,BU706,BU908)
2SC3686	Si-NPN	TV-HD,Hi-def,1500/800V,7A,120W	18j$	Sanyo	2SC3687,BU4508AX,(BU508A,BU908)
2SC3687	Si-NPN	TV-HD,Hi-def,1500/800V,8A,150W	18j$	Sanyo	BU2520A
2SC3688	Si-NPN	TV-HD,Hi-def,1500/800V,10A,150W	18j$	Sanyo	BU2520A,BU4530AW
2SC3689	Si-NPN	Hi-Ueb,Hi-beta,60V,0,1A,B=1500	35a	Sanyo	2SC3651,(2SC4413)
2SC369(G)	Si-NPN	=2SC368:0,2W	7c	Tos	BC169,BC184,BC239,BC549,2SC2675+
2SC3690	Si-NPN	Sw,Pow,Lo-sat,100V,3A,15W,<300/1800nS	17c	Nec	2SC3695
2SC3691	Si-NPN	Sw,Pow,100V,5A,25W,<300/1800nS	17c	Nec	2SC3696,2SC4549
2SC3692	Si-NPN	Sw,Pow,100V,7A,30W,<300/1800nS	17c	Nec	2SC3697,2SC4550
2SC3693	Si-NPN	Sw,Pow,100V,10A,30W,<300/1800nS	17c	Nec	2SC3698,2SC4551
2SC3694	Si-NPN	Sw,Pow,100V,15A,30W,<300/1800nS	17c	Nec	2SC3699,2SC4552
2SC3695	Si-NPN	Sw,Pow,150/150V,3A,15W,<300/1800nS	17c	Nec	-
2SC3696	Si-NPN	Sw,Pow,150V,5A,20W,<300/1800nS	17c	Nec	-
2SC3697	Si-NPN	Sw,Pow,150V,7A,25W,<300/1800nS	17c	Nec	-
2SC3698	Si-NPN	Sw,Pow,150V,10A,30W,<300/1800nS	17c	Nec	-

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2SC3699	Si-NPN	Sw,Pow,150V,15A,30W,<300/1800nS	17c	Nec	-
2SC37	Si-NPN	HF-Dr,40V,0,1A,0,2W,200MHz	2a$	Nec	BFW16..17,BFX55
2SC370(G,T)	Si-NPN	GenP,35..40V,0,1A,0,2W,200MHz,B>20	7c	Tos	BC167,BC183,BC237,BC547,2SD767..
2SC3700	Si-NPN	UHF-Pow,55V,6A,Pq=30W(860MHz)	61s*	Fui	-
2SC3701	Si-NPN	UHF-Pow,55V,12A,Pq=50W(860MHz)	61s*	Fui	-
2SC3702	Si-NPN	UHF-Pow,55V,20A,Pq=80W(860MHz)	61s*	Fui	-
2SC3703	Si-NPN	Sw,Pow,230/230V,30A,300W,<0,7/2µS	68a$	Shi	2SC2940,2SC3224
2SC3704	Si-NPN	UHF,LN,15V,0,08A,6GHz	35a	Mat	2SC3356,2SC3445,2SC3606
2SC3705	Si-N-Darl+Di	AF,Sw-Pow,50V,1,2A,10W,180MHz,B=4000	14h$	Sanyo	-
2SC3706	Si-NPN	Sw,Pow,230/230V,50A,200W,<1,2/2,5µS	68a$	Sak	2SC1437,2SC2942
2SC3707	Si-NPN	UHF,10V,0,01A,4GHz	35a	Mat	BFR92,2SC3099,2SC3110
2SC3708	Si-NPN	GenP,100V,0,5A,0,6W,120MHz	7c	Sanyo	BC639,2SC2235,2SD667,2SD1768..
2SC3709(A)	Si-NPN	Lo-sat,60V,12A,30W,90MHz,200/1200nS	17c	Tos	2SC4065
2SC371(G,T)	Si-NPN	=2SC370:30V,B>40	7c	Tos	BC167,BC183,BC237,BC547,2SD767..
2SC3710	Si-NPN	=2SC3709:80V,80MHz	17c	Tos	2SC4595
2SC3711	Si-NPN	GenP,60V,0,1A,0,2W,200MHz	41c	Tos	BC174,BC182,BC190,BC546,2SD767..
2SC3712	Si-NPN	UHF-Pow,35V,16A,Pq>50..60W(860MHz)	61v	Nec	-
2SC3713	Si-NPN	GenP,60V,0,1A,200MHz	35a	Tos	BC846,BCV71..72,2SC3323..
2SC3714	Si-NPN	Sw,Pow,500/400V,20A,200W,<500/2300nS	77j$	Shi	2SC3498..99
2SC3715	Si-NPN+Diode	TV-HD,1500/600V,4A,50W,<2/5,5µS	18c	Tos	BU706DF,2SC3480,2SC4293,2SD1554..55..
2SC3716	Si-NPN	TV-HD,1500/600V,5A,50W,<2/5,5µS	18c	Tos	BU706F,2SC4142,2SD1545,2SD1655..
2SC3717	Si-NPN	FM/VHF,30V,0,05A,0,2W,750MHz	41c	Tos	BF225,BF255,BF310,BF314,BF496..
2SC3718	Si-NPN	=2SC3717:SMD	35a	Tos	BF599,BF799,2SC3015,2SC3374
2SC3718-O	Si-NPN	-	35	Tos	→2SC3718
2SC3718-Y	Si-NPN	-	35	Tos	→2SC3718
2SC3719	Si-NPN	Sw,Pow,TV-HD,1200/800V,5A,150W	23a$	Matsushita	-
2SC372(G,GTM)	Si-NPN	GenP,35V,0,1A,0,2W,200MHz,B>70	7c	Tos	BC167,BC183,BC237,BC547,2SD767..
2SC3720	Si-NPN	Sw,Pow,TV-HD,1200/800V,10A,200W	23a$	Matsushita	-
2SC3721	Si-NPN	UHF,15V,0,05A,0,2W,7GHz	25za	Hit	BFG65,BFQ66,2SC3062,2SC3584
2SC3722	Si-NPN	AF,LN,120V,0,05A,140MHz	?35d	Rhm	-
2SC3722K	Si-NPN	=2SC3722:	35a	-	2SC3324,2SC4050
2SC3722K-E	Si-NPN	-	35	Rhm	→2SC3722K
2SC3722K-R	Si-NPN	-	35	Rhm	→2SC3722K
2SC3722K-S	Si-NPN	-	35	Rhm	→2SC3722K
2SC3723	Si-NPN	Sw,Pow,450/400V,5A,40W,<1/3µS	17j$	Fjd	MJE53T,2SC2542,2SC2827,2SC3056..
2SC3724	Si-NPN	Sw,Pow,450/400V,10A,80W,<1/3µS	18j$	Fjd	BUP23,2SC2625,2SC3042,2SC4138..
2SC3725	Si-NPN	Sw,Pow,450/400V,15A,80W,<1/3µS	18j$	Fjd	BUP23,2SC3520,2SC3435,2SC4139..
2SC3726	Si-NPN	Hi-beta,50V,2A,0,9W,150MHz,B=1200	7c(9mm)	Mit	2SD1779
2SC3727	Si-NPN	=2SC3726:SMD	39b	Mit	-
2SC3728	Si-NPN+Diode	20V,2A,80MHz	39b	Mit	-
2SC3728-E	Si-NPN	-	39	Mit	→2SC3728
2SC3728-F	Si-NPN	-	39	Mit	→2SC3728
2SC3728-G	Si-NPN	-	39	Mit	→2SC3728
2SC3729	Si-NPN	Sw,Pow,TV-HD,1500/800V,5A,50W	18j$	Hit	BU706,BU2508A,2SC3485,2SC3685..
2SC373	Si-NPN	35V,0.1A,0.2W,B>200	-		-
2SC373(G,GTM)	Si-NPN	=2SC372:B>200	7c	Tos	BC167,BC183,BC237,BC547,2SD767..
2SC3730	Si-NPN	UHF,LN,15V,0,05A,7,5GHz	35a	Hit	BFQ67,BFR183,2SC3445,2SC3583
2SC3731	Si-NPN	Sw,60V,0,2A,0,25W,<70/250nS	40c	Nec	2SC1834
2SC3732	Si-NPN	HF/Sw,40V,0,2A,0,25W,<12/18nS	40c	Nec	BSS11,2N2368..B9(A),2SC2901
2SC3733	Si-NPN	HF/Sw,80V,1A,1W,<40/110nS	9b	NEC	-
2SC3734	Si-NPN	=2SC3731:SMD	35a	Nec	-
2SC3734-B22	Si-NPN	-	35	Nec	→2SC3734
2SC3734-B23	Si-NPN	-	35	Nec	→2SC3734
2SC3734-B24	Si-NPN	-	35	Nec	→2SC3734
2SC3735	Si-NPN	=2SC3732:SMD	35a	Nec	-
2SC3735-B33	Si-NPN	-	35	Nec	→2SC3735
2SC3735-B34	Si-NPN	-	35	Nec	→2SC3735
2SC3735-B35	Si-NPN	-	35	Nec	→2SC3735
2SC3736	Si-NPN	=2SC3733:SMD	39b	Nec	-
2SC3736-OK	Si-NPN	-	39	Nec	→2SC3736
2SC3736-OL	Si-NPN	-	39	Nec	→2SC3736
2SC3737	Si-NPN	Sw,Pow,1200/800V,5A,100W,<1/3,8µS	16c	Mat	2SC4584,2SC4882
2SC3738	Si-NPN	Sw,Pow,1200/800V,10A,175W,<1/3,8µS	77j$	Mat	2SC4096
2SC3739	Si-NPN	HF/Sw,60V,0,5A,<35/275nS	35a	NEC	BSR13..14,BSS79,BSS81,2N3302

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2SC3739-B12	Si-NPN	-	3S	Nec	→2SC3739
2SC3739-B13	Si-NPN	-	3S	Nec	→2SC3739
2SC3739-B14	Si-NPN	-	3S	Nec	→2SC3739
2SC374	Si-NPN	GenP,35V,0,1A,0,2W,150MHz	7c	Tos	BC167,BC183,BC237,BC547,2SD767..
2SC3740	Si-NPN	Sw,30V,1A,0,75W,<1/3µS	7c	Nec	BC635,BC637,2SD1225,2SD1051..
2SC3741	Si-NPN	=2SC3740:	40c	Nec	→2SC3739
2SC3742	Si-NPN	=2SC3740: SMD	35a	Nec	-
2SC3743	Si-NPN	Sw,Pow,900/800V,3A,40W,<1/5µS	17c	Mat	BUT11AF,2SC3559,2SC3752,2SC4304..
2SC3744	Si-NPN	GenP,180/180V,0,1A,100MHz	35a	Hit	2SC3143,2SD1305
2SC3745	Si-NPN	UHF,20V,0,03A,6,5GHz	44ze	Tos	2SC4095
2SC3746	Si-NPN	Sw,Pow,Lo-sat,80V,5A,20W,100/600nS	17c	Sanyo	2SC4540,2SC3691,2SC4549,2SC4596
2SC3747	Si-NPN	Sw,Pow,Lo-sat,80V,7A,25W,100/600nS	17c	Sanyo	2SC3692,2SC4550
2SC3748	Si-NPN	Sw,Pow,Lo-sat,80V,10A,30W,100/600nS	17c	Sanyo	2SC3693,2SC4551
2SC3749	Si-NPN	Sw,Pow,800/500V,3A,25W,<500/3300nS	17c	Sanyo	2SC3559,2SC4304,2SD1571
2SC375	Si-NPN	VHF,20V,50mA,600MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3750	Si-NPN	Sw,Pow,800/500V,5A,30W,<500/3300nS	17c	Sanyo	BUT11(A)F,2SC3353,2SC3795(A)
2SC3751	Si-NPN	Sw,Pow,1100/800V,1,5A,25W,<500/3300nS	17c	Sanyo	2SC4231
2SC3752	Si-NPN	Sw,Pow,1100/800V,3A,30W,<500/3300nS	17c	Sanyo	2SC4234
2SC3753	Si-NPN+Diode	Sw,Pow,TV-HD,1500/800V,5A,60W	18c	Sanyo	BU706DF,2SC4293..94,2SD1651..52..
2SC3754	Si-NPN+Diode	Sw,Pow,TV-HD,1500/800V,6A,60W	18c	Sanyo	BU2508DF,2SC4294,2SC4122,2SD1652..
2SC3755	Si-NPN	Sw,Pow,TV-HD,1500/800V,5A,60W	18c	Sanyo	BU706,2SC3894,2SC4142..43,2SD1545,..
2SC3756	Si-NPN	Sw,Pow,TV-HD,1500/800V,6A,60W	18c	Sanyo	BU2508AF,2SC3894,2SC4143,2SD1546..
2SC3757	Si-NPN	Sw,40V,0,1A,17/17nS	35a	Matsushita	2SC3578,2SC4168
2SC3757-Q	Si-NPN	-	3S	Mat	→2SC3757
2SC3757-R	Si-NPN	-	3S	Mat	→2SC3757
2SC3757-S	Si-NPN	-	3S	Mat	→2SC3757
2SC3758	Si-NPN	Sw,Pow,500/400V,10A,70W,<300/1800nS	18c	Nec	2SC4296,2SC4423
2SC3759	Si-NPN	Sw,Pow,500/400V,15A,75W,<500/1800nS	18c	Nec	2SC4298,2SC4424
2SC376	Si-NPN	GenP,70V,0,1A,0,2W,150MHz	7c	Tos	BC174,BC182,BC190,BC546,2SC1890+
2SC3760	Si-NPN	Sw,Pow,500/400V,10A,65W,<1000/3200nS	18c	Nec	2SC4296,2SC4423
2SC3761	Si-NPN	Sw,Pow,500/400V,15A,75W,<1000/3200nS	18c	Nec	2SC4298,2SC4424
2SC3762	Si-NPN	Sw,Pow,150/100V,15A,65W,<1000/1800nS	18c	Nec	2SC4886
2SC3763	Si-NPN	Sw,Pow,1000/800V,3A,60W,<1000/3500nS	18c	Nec	2SC4426,2SC4583
2SC3764	Si-NPN	Sw,Pow,1000/800V,4A,65W,<1000/3500nS	18c	Nec	2SC4427,2SC4882
2SC3765	Si-NPN	Sw,Pow,1000/800V,6A,70W,<1000/3500nS	18c	Nec	2SC4428,2SC4584
2SC3766	Si-NPN	Sw,Pow,1000/800V,8A,75W,<1000/3500nS	18c	Nec	2SC4429
2SC3769	Si-NPN	TV-HD,1500/600V,8A,50W,<500/5500nS	23a$	Hitachi	BU2508A,BU908,2SC3027..3028
2SC377	Si-NPN	HF,35V,0,03A,0,2W,150MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3770	Si-NPN	VHF/UHF,30V,0,03A,1200MHz	35a	Sanyo	BF517,BFS17,2SC3005,2SC3016
2SC3771	Si-NPN	VHF/UHF,30V,0,03A,2200MHz	35a	Sanyo	BFR35,BFR53,BFT25,2SC3014
2SC3772	Si-NPN	UHF,25V,0,07A,3000MHz	35a	Sanyo	BFR106,2SC3161,2SC3774..75
2SC3773	Si-NPN	UHF,25V,0,05A,3500MHz	35a	Sanyo	BF770A,BFT75,2SC3014
2SC3774	Si-NPN	UHF,20V,0,07A,5000MHz	35a	Sanyo	2SC3161,2SC3704
2SC3775	Si-NPN	UHF,20V,0,1A,5000MHz	35a	Sanyo	BFR106,2SC3356
2SC3776	Si-NPN	UHF,25V,0,07A,3000MHz	7f	Sanyo	2SC2570(A),2SC3037,2SC3337
2SC3777	Si-NPN	UHF,25V,0,05A,3500MHz	7f	Sanyo	2SC2498,2SC2570(A),2SC3037,2SC3337
2SC3778	Si-NPN	UHF,20V,0,07A,5000MHz	7f	Sanyo	2SC2570(A),2SC3037,2SC3337
2SC3779	Si-NPN	UHF,20V,0,1A,5000MHz	7f	Sanyo	2SC3355
2SC378	Si-NPN	HF,35V,0,03A,0,2W,150MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3780	Si-NPN	Vid-Out,Hi-def,80V,0,8A,15W,800MHz	17j$	Sanyo	-
2SC3781	Si-NPN	Vid-Out,Hi-def,120V,0,4A,15W,500MHz	17j$	Sanyo	-
2SC3782	Si-NPN	Vid-Out,Hi-def,200V,0,2A,15W,400MHz	17j$	Sanyo	-
2SC3783	Si-NPN	Sw,Pow,900/800V,5A,100W,<1/4,5µS	18j$	Tos	BUW11A,BUW131A,BUV82,2SC3796A..
2SC3784	Si-N-Darl+Di	50V,1,2A,20W,180MHz,B=4000	?14h$	Sanyo	-
2SC3785	Si-N-Darl+Di	50V,2A,20W,180MHz,B=4000	?14h$	Sanyo	-
2SC3786	Si-N-Darl+Di	50V,3A,20W,180MHz,B=4000	?14h$	Sanyo	-
2SC3787	Si-NPN	AF-Driver,180V,0,14A,10W,150MHz	14b	Sanyo	2SC3956,(BF415,BF417,2SC3601,..)
2SC3788	Si-NPN	Vid-Out,Hi-def,200V,0,1A,5W,150MHz	14b	Sanyo	2SC3955..56,(2SC3502..03)
2SC3789	Si-NPN	Vid-Out,Hi-def,300V,0,1A,7W,70MHz	14b	Sanyo	(2SC3417,2SC3503)
2SC379	Si-NPN	HF,30V,0,1A,0,2W,300MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3790	Si-NPN	Vid-Out,Hi-def,300V,0,1A,7W,150MHz	14b	Sanyo	(2SC3417,2SC3503)
2SC3791	Si-NPN	UHF,LN,15V,0,08A,0,25W,6GHz	25za	Mat	BFQ82,2SC3358,2SC3603
2SC3792	Si-NPN	50V,Ueb=25V,0,5A,0,5W,250MHz,B>300	7c	Sanyo	2SC2935,2SD1582
2SC3793	Si-NPN	UHF-Osc,20V,0,05A,2900MHz	35a	Hit	BFT75,2SC3014,2SC3773

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2SC3794	Si-NPN	Sw,Pow,800/500V,1,5A,25W,<1/4µS	17c	Mat	BUX84F..85F,2SC3352,2SC3978
2SC3794A	Si-NPN	=2SC3794:900/500V,<1,2/4,2µS	17c	-	BUX85F,2SC3751,2SC3978,2SC4231
2SC3795	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/4µS	17c	Mat	BUT11(A)F,2SC3353,2SC3750,2SC4518
2SC3795A	Si-NPN	=2SC3795:900/500V,<1,2/4,2µS	17c	-	BUT11AF,BUT18AF,BUT21CF,2SC4518
2SC3796	Si-NPN	Sw,Pow,800/500V,5A,70W,<1/4µS	18j$	Mat	BUW11(A),BUW131(A),2SC3089,2SC3636+
2SC3796A	Si-NPN	=2SC3796:900/500V,<1,2/4,2µS	18j$	-	BUW11A,BUW131A,2SC3636,2SC3642..
2SC3797	Si-NPN	Sw,Pow,800/500V,7A,100W,<1/4µS	18j$	Mat	BUV47(A),BUW12(A),2SC3449,2SC3636,+
2SC3797A	Si-NPN	=2SC3797:900/500V,<1,2/4,2µS	18j$	-	BUV47A,BUW12A,2SC3466,2SC3636..
2SC3798	Si-NPN	Sw,Pow,800/500V,5A,70W,<1/4µS	16c	Mat	BUW11(A)F,2SC4300,2SC4457
2SC3798A	Si-NPN	=2SC3798:900/500V,<1,2/4,2µS	16c	-	BUW11AF,2SC4300,2SC4427
2SC3799	Si-NPN	Sw,Pow,800/500V,7A,100W,<1/4µS	16c	Mat	BUV47(A)FI,BUW12(A)F,2SC4301
2SC3799A	Si-NPN	=2SC3799:900/500V,<1,2/4,2µS	16c	-	BUV47AFI,BUW12AF,2SC4301,2SC4429
2SC38	Si-NPN	=2SC37:0,5W	2a$	Nec	BFW16..17,BFX55
2SC380(TM,ATM)	Si-NPN	FM-IF,35V,30mA,250MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3800	Si-NPN	GenP,LN,150V,0,05A,0,8W,140MHz	7c(9mm)	Rhm	2SC2632
2SC3801	Si-NPN	UHF,30V,0,03A,0,25W,1100MHz	7f	Rhm	BF377..378,BF763,2SC2570(A)..
2SC3802K	Si-NPN	=2SC3801:SMD	35a	Rhm	BFS17,BFS17,2SC3016,2SC3161
2SC3802K-M	Si-NPN	-	35	Rhm	→2SC3802K
2SC3802K-N	Si-NPN	-	35	Rhm	→2SC3802K
2SC3802K-P	Si-NPN	-	35	Rhm	→2SC3802K
2SC3802K-Q	Si-NPN	-	35	Mat	→2SC3802K
2SC3803	Si-NPN	GenP,60V,0,2A,200MHz	39b	Tos	-
2SC3803-O	Si-NPN	-	39	Tos	→2SC3803
2SC3803-R	Si-NPN	-	39	Tos	→2SC3803
2SC3803-Y	Si-NPN	-	39	Tos	→2SC3803
2SC3804	Si-NPN	UHF-Pow,35V,12A,Pq=45W(860MHz)	61t	Mit	-
2SC3805	Si-NPN	HF/Vid-Pow,300/300V,0,1A,10W,70MHz	30j$	Tos	2SC2870,2SC3408,2SC2924,2SC4019
2SC3806	Si-NPN	UHF,LN,15V,0,05A,0,15W,4500MHz	5g	Hit	BFQ63
2SC3807	Si-NPN	Hi-beta,Lo-sat,Hi-Ueb,30V,2A,B>800	?14h	Sanyo	-
2SC3808	Si-NPN	Hi-beta,Lo-sat,Hi-Ueb,80V,2A,B>800	?14h	Sanyo	-
2SC3809	Si-NPN	Dual,UHF,20V,2x0,1A,0,3W,7GHz	-	Nec	-
2SC380TM	Si-NPN	30V,50mA,0.3W,100MHz	-		-
2SC381	Si-NPN	FM-IF,40V,20mA,>250MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3810	Si-NPN	Dual,UHF,20V,2x65mA,0,3W,8GHz	-	Nec	-
2SC3811	Si-NPN	Sw,40V,0,1A,0,4W,450MHz,17/17nS	7e	Mat	BSV91..92,BSX92..93,2N2360(A)..
2SC3812	Si-NPN	Dual,VHF-Pow,55V,48A,Pq=200W(230MHz)	-	Nec	-
2SC3813	Si-NPN	Sw,Pow,300/100V,7A,150W,10MHz	18j$	Tos	TIP55A..58A,2SC2305,2SC2656..
2SC3814	Si-NPN	UHF-Pow,20V,0,5A,Pq=1W(940MHz)	-	Nec	-
2SC3815	Si-NPN	UHF-Pow,20V,1,5A,Pq=3,2W(940MHz)	-	Nec	-
2SC3816	Si-NPN	UHF-Pow,20V,3A,Pq=6,3W(940MHz)	-	Nec	-
2SC3817	Si-NPN	UHF-Pow,35V,0,5A,Pq=1W(1550MHz)	61r	Nec	-
2SC3818	Si-NPN	UHF-Pow,35V,2A,Pq=4W(1550MHz)	61r	Nec	-
2SC3819	Si-NPN	UHF-Pow,35V,4A,Pq=10W(1550MHz)	61r	Nec	-
2SC382(TM)	Si-NPN	TV-IF,VHF-AGC,600MHz	7c	Tos	BF198,BF225,BF310,BF367,BF505..
2SC3820	Si-NPN	Hi-beta,Hi-Ueb,60V,0,1A,B=1500	40c	Sanyo	2SC3069,2SC3071,2SC3836,(2SC3622)
2SC3821	Si-NPN	Sw,Pow,450/400V,5A,40W,<1/3,5µS	17c	Fjd	2SC3570,2SC3573,2SC4073,2SC4371..
2SC3822	Si-NPN	Sw,Pow,450/400V,5A,30W,<1/3,5µS	17c	Fjd	2SC3570,2SC3573,2SC4073,2SC4371..
2SC3823	Si-NPN	Sw,Pow,120/80V,5A,40W,<1/3,5µS	17j$	Hit	BDV10..12,MJE15028,2SD772
2SC3824(A)	Si-NPN	=2SC3496(A):15W	?30j$	Mat	-
2SC3825	Si-NPN	=2SC3403:15W	?30j$	Mat	2SC3233,2SC3631
2SC3826	Si-NPN	Sw,Pow,200/100V,5A,30W,<500/2800nS	17j$	Nec	2SC2767,2SD772A,B
2SC3827	Si-NPN	UHF-Osc,30V,0,02A,1300MHz	35a	Nec	BF517,BFS17,2SC3005,2SC3016
2SC3828	Si-NPN	TV-UHF-Tuner,25V,0,02A,1100MHz	44zf	Tos	-
2SC3829	Si-NPN	UHF,15V,0,08A,6000MHz	35a	Mat	BFR193,2SC3445,2SC3606,2SC3704
2SC383	Si-NPN	TV-IF-Out,75V,0,05A,0,3W,>300MHz	7c	Tos	(BF199,BF224,BF311,BF373,..)
2SC3830	Si-NPN	Sw-Reg,600/500V,6A,50W,<1/5µS	17j$	Sak	MJE13006,MJE13070,2SC3087,2SC4055..
2SC3831	Si-NPN	Sw-Reg,600/500V,10A,100W,<1/5µS	18j$	Sak	BUP23,2SC3090,2SC3450,2SC4058..
2SC3832	Si-NPN	Sw-Reg,500/400V,7A,50W,<1/3,5µS	17j$	Sak	MJE13006,2SC3039,2SC3170,2SC4106..
2SC3833	Si-NPN	Sw-Reg,500/400V,12A,100W,<1/3,5µS	18j$	Sak	BUP23,2SC3520,2SC4139,2SC4434..
2SC3834	Si-NPN	Sw-Reg,200/120V,7A,50W,<500/3500nS	17j$	Sak	BU406..409,TIP150..152,2SC4848..
2SC3835	Si-NPN	Sw-Reg,200/120V,7A,70W,<500/3500nS	18j$	Sak	TIP55A..58A,2SC2305,2SC2656..
2SC3836	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,60V,0,3A,B>800	41c	Hit	-
2SC3837K	Si-NPN	VHF/UHF,30V,0,05A,1500MHz	35a	Rohm	BFS17,BF799,2SC3015..16,2SC3161..
2SC3837K-L	Si-NPN	-	35	Rhm	→2SC3837K

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2SC3837K-M	Si-NPN	-	3S	Rhm	→2SC3837K
2SC3837K-N	Si-NPN	-	3S	Rhm	→2SC3837K
2SC3837K-P	Si-NPN	-	3S	Rhm	→2SC3837K
2SC3837K-Q	Si-NPN	-	3S	Rhm	→2SC3837K
2SC3838K	Si-NPN	UHF,20V,0,05A,3200MHz	35a	Rhm	BF775,2SC3014,2SC3098,2SC3773..
2SC3838K-L	Si-NPN	-	3S	Rhm	→2SC3838K
2SC3838K-M	Si-NPN	-	3S	Rhm	→2SC3838K
2SC3838K-N	Si-NPN	-	3S	Rhm	→2SC3838K
2SC3838K-P	Si-NPN	-	3S	Rhm	→2SC3838K
2SC3838K-Q	Si-NPN	-	3S	Rhm	→2SC3838K
2SC3839K	Si-NPN	VHF/UHF,30V,0,05A,2000MHz	35a	Rohm	BFR53,2SC3014,2SC3098,2SC3773..
2SC3839K-L	Si-NPN	-	3S	Rhm	→2SC3839K
2SC3839K-M	Si-NPN	-	3S	Rhm	→2SC3839K
2SC3839K-N	Si-NPN	-	3S	Rhm	→2SC3839K
2SC3839K-P	Si-NPN	-	3S	Rhm	→2SC3839K
2SC3839K-Q	Si-NPN	-	3S	Rhm	→2SC3839K
2SC383TM,ATM	Si-NPN	=2SC383:50(ATM=30V)	7c	-	BF199,BF224,BF311,BF373..
2SC384	Si-NPN	VHF,20V,0,05A,0,2W,500MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3840	Si-NPN	Sw,Pow,600/600V,1A,15W,30MHz	14h$	Nec	BUX99,(BUV63,2SC3632)
2SC3841	Si-NPN	UHF-Mix/Osc,25V,0,03A,4GHz	35a	Nec	BFQ29,BFQ81,BFR93,BFT75
2SC3841-T62	Si-NPN	-	3S	Nec	→2SC3841
2SC3841-T63	Si-NPN	-	3S	Nec	→2SC3841
2SC3841-T64	Si-NPN	-	3S	Nec	→2SC3841
2SC3842	Si-NPN	Sw,Pow,TV-HD,600/400V,10A,70W,32MHz	18c	Fui	2SC4459,2SC4587
2SC3843	Si-NPN	Sw,Pow,TV-HD,600/450V,10A,75W28MHz	18c	Fui	2SC4459,2SC4587
2SC3844	Si-NPN	Sw,Pow,TV-HD,600/450V,15A,75W30MHz	18c	Fui	BUP23BF,BUV48FI,BUW13F
2SC3845	Si-NPN	Sw,Pow,TV-HD,1200/800V,3A,75W15MHz	18c	Fui	2SC4583,(2SC3387,2SC3642)
2SC3846	Si-NPN	Sw,Pow,TV-HD,1200/800V,6A,80W,15MHz	18c	Fui	2SC4584,(BUV89,2SC3466,2SC3643)
2SC3847	Si-NPN	Sw,Pow,TV-HD,1200/800V,10A,85W15MHz	18c	Fui	BU2520AF,2SC4199,(BUV70..71)
2SC3848	Si-NPN	VHF,25V,0,2A,500MHz	35a	Rhm	-
2SC3849	Si-NPN	Dual,UHF-E,20V,0,08A,7GHz	-	Rhm	-
2SC385(A)	Si-NPN	VHF,20V,0,02A,0,2W,600MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3850	Si-NPN	Sw,Pow,500/400V,20A,125W,<1/3,5µS	18j$	Mat	2SC4110
2SC3851	Si-NPN	AF,Sw-Pow,Lo-sat,80V,4A,25W,15MHz	17c	Sak	2SC3691,2SC3746,2SC4549,2SC4596..
2SC3851A	Si-NPN	=2SC3851:100V	17c	-	2SC3540,2SC3691,2SC4549,2SC4596..
2SC3852	Si-NPN	Hi-beta,Lo-sat,80V,3A,25W,15MHz,B>500	17c	Sak	2SD2092,(2SD1944,2SD1273A,2SD2156A..)
2SC3852A	Si-NPN	=2SC3852:100V	17c	-	2SD2092,(2SD1273A,2SD2156A,..)
2SC3853	Si-NPN	AF,Sw-Pow,120/80V,6A,60W,20MHz	18j$	Sak	BD245D,BD545D,2SC4466,2SD896..
2SC3854	Si-NPN	AF,Sw-Pow,160/120V,8A,80W,20MHz	18j$	Sak	BD245D,2SC4467,2SD751
2SC3855	Si-NPN	AF,Sw-Pow,200/140V,10A,100W,20MHz	18j$	Sak	BD245F,2SC3263,2SC4468
2SC3856	Si-NPN	AF,Sw-Pow,200/180V,15A,130W,20MHz	18j$	Sak	BD249F,2SC3263
2SC3857	Si-NPN	AF,Sw-Pow,200/200V,15A,150W,20MHz	20j$	Sak	2SC2773..2774,2SC3370,2SD846
2SC3858	Si-NPN	AF,Sw-Pow,200/200V,17A,200W,20MHz	20j$	Sak	2SC2774,2SC3264
2SC3859	Si-NPN	-	3S	Sanyo	→2SC3859
2SC386(A)	Si-NPN	VHF,20V,0,02A,500(A=600)MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3860	Si-NPN-Digital	Sw,50V,0,1A,0,3W,250MHz,R1=10kΩ	40c	Sanyo	AA1A4Z,DTC114TS,RN1011,UN4215..
2SC3861	Si-NPN	UHF,10V,0,01A,0,07W,4GHz	7f	Mat	2SC2499,2SC2570(A),2SC3512
2SC3862	Si-NPN	TV-UHF-Tuner,30V,0,05A,2400MHz	35d	Tos	-
2SC3863	Si-NPN	-	3S	Sanyo	→2SC3863
2SC3864	Si-NPN-Digital	Sw,R1=2,2kΩ,R2=10kΩ,50V,0,1A,0,3W,250MHz	40c	Sanyo	DTC123YS,UN421H
2SC3865	Si-NPN	Sw-Reg,500/400V,5A,40W,<500/1650nS	17c	Fjd	2SC3497,2SC3570,2SC3573,2SC4054..
2SC3866	Si-NPN	Sw,Pow,900/800V,3A,40W,<1000/4800nS	17c	Fjd	2SC3559,2SC4303 2SC4517,2SC4908
2SC3867	Si-NPN	UHF,20V,0,05A,3800MHz	35d	Hit	-
2SC3868	Si-NPN	Sw,Pow,500/400V,1,5A,25W,<700/2300nS	17c	Mat	2SC3309,2SC3560..61,2SC3569
2SC3869	Si-NPN	Sw,Pow,500/400V,5A,35W,<700/2300nS	17c	Mat	2SC3497,2SC3570,2SC3573,2SC4054..
2SC387(A,G,GTM)	Si-NPN	UHF,20V,0,05A,900(A=1200)MHz	7c	Tos	BF377..378,BF689K,BF763,2SC2570,..
2SC3870	Si-NPN	Sw,Pow,500/400V,7A,40W,<700/2300nS	17c	Mat	2SC3571,2SC3574,2SC4130,2SC4161..
2SC3871	Si-NPN	Sw,Pow,500/400V,10A,45W,<700/2300nS	17c	Mat	2SC3572,2SC3575,2SC4162,2SD1795..
2SC3872	Si-NPN	Sw,Pow,500/400V,10A,70W,<700/2300nS	16c	Mat	2SC4296..97,2SC4423
2SC3873	Si-NPN	Sw,Pow,500/400V,12A,100W,<700/2300nS	16c	Mat	2SC4297,2SC4423
2SC3874	Si-NPN	Sw,Pow,500/400V,15A,150W,<700/2300nS	77j$	Mat	2SC3714
2SC3875	Si-NPN	GenP,LN,60V,0,15A,130MHz	35b	Kec	-
2SC3876	Si-NPN	GenP,35V,0,5A,300MHz	35b	Kec	-
2SC3877	Si-NPN	GenP,LN,120V,0,1A,100MHz	35b	Kec	-

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2SC3878	Si-NPN	GenP,LN,35V,0,1A,120MHz	35b	Kec	-
2SC3879	Si-NPN	FM-IF,35V,0,05A,175MHz	35b	Kec	-
2SC3880(A,ATM)	Si-NPN	TV-IF,20(A=25)V,0,02A,450MHz	7c	Tos	BF198..199,BF224..225,BF505..
2SC3880	Si-NPN	FM/VHF,40V,0,02A,550MHz	35b	Kec	-
2SC3881	Si-NPN	FM/VHF,30V,0,05A,600MHz	35b	Kec	-
2SC3883	Si-NPN+Diode	TV-HD,1500/800V,5A,50W	1Bj$	Hit	BU706D,2SC3481,2SC3681,2SC4291..
2SC3884	Si-NPN	SN,HD,Hi-res,1400/600V,6A,50W	18c	Tos	2SC3894,2SC4757,2SC4830
2SC3884A	Si-NPN	=2SC3884:1500/600V	18c	-	2SC3894,2SC4757,2SC4830,BU4508AX
2SC3885	Si-NPN	SN,HD,Hi-res,1400/600V,7A,50W	18c	Tos	2SC3895,2SC4757
2SC3885A	Si-NPN	=2SC3885:1500/600V	18c	-	2SC3895,2SC4757,BU4515AX
2SC3886	Si-NPN	SN,HD,Hi-res,1400/600V,8A,50W	18c	Tos	2SC3896,2SC4758
2SC3886A	Si-NPN	=2SC3886:1500/600V	18c	-	2SC3896,2SC4758,BU4522AX
2SC3887(A)	Si-NPN	=2SC3884(A):80W	77c,j$	Tos	2SC3486,2SC3685
2SC3888(A)	Si-NPN	=2SC3885(A):80W	77c,j$	Tos	2SC3686
2SC3889(A)	Si-NPN	=2SC3886(A):80W	77c,j$	Tos	2SC3687
2SC389	Si-NPN	VHF,20V,0,02A,500MHz	5g	Tos	BF199,BF224,BF310,BF314,BF505..
2SC3890	Si-NPN	Sw-Reg,500/400V,7A,30W,<1000/3500nS	17c	Sak	2SC3571,2SC3574,2SC4130,2SC4161..
2SC3891	Si-NPN+Diode	=2SC3884:Int.Damper-Diode	18c	Tos	2SC4764
2SC3892	Si-NPN+Diode	=2SC3885:Int.Damper-Diode	18c	Tos	2SC4762,2SC4916
2SC3892A	Si-NPN+Diode	=2SC3885A:Int.Damper-Diode	18c	-	2SC4762,2SC4916,BU4508DX
2SC3893	Si-NPN+Diode	=2SC3886:Int.Damper-Diode	18c	Tos	2SC4763,2SC5043
2SC3893A	Si-NPN+Diode	=2SC3886A:Int.Damper-Diode	18c	-	2SC4763,2SC5043,BU4522DX
2SC3894	Si-NPN	HD,Hi-def,1500/800V,6A,60W	18c	Sanyo	2SC3884A..85A,2SC4830,BU4507AX
2SC3895	Si-NPN	HD,Hi-def,1500/800V,7A,60W	18c	Sanyo	2SC3885A,2SC4757,BU4508AX
2SC3896	Si-NPN	HD,Hi-def,1500/800V,8A,70W	18c	Sanyo	2SC3886A,2SC4758,2SC5148,BU4522AX
2SC3897	Si-NPN	HD,Hi-def,1500/800V,10A,70W	18c	Sanyo	BU2520AF,2SC4542,2SC4759,BU4530AL
2SC3898	Si-NPN	-	3S	Sanyo	→2SC3898
2SC3899	Si-NPN-Digital	Sw,50V,0,1A,0,3W,250MHz,R1=47kΩ	40c	Sanyo	AA1L4Z,DTC144TS,RN1013,UN4210..
2SC39(A)	Si-NPN	HF,25V,0,05A,0,25W,350..500MHz	2a$	Fui	BF198..199,BF224..225,BF505..
2SC390(D)	Si-NPN	VHF/UHF,30V,0,02A,1000MHz	5g	Tos	BF377..378,BF689,BF763,2N2857..
2SC3900	Si-NPN	-	3S	Sanyo	→2SC3900
2SC3901	Si-NPN-Digital	Sw,50V,0,1A,0,3W,250MHz,R1=4,7kΩ	40c	Sanyo	AA1L3Z,DTC143TS,RN1010,UN4216..
2SC3902	Si-NPN	TV-AF-Pow,180/160V,1,5A,10W,120MHz	14b	Sanyo	(2SC3117,2SD669)
2SC3903	Si-NPN	UHF,15V,65mA,0,15W,8,5GHz	25za	Mat	2SC3584
2SC3904	Si-NPN	-	3S	Mat	→2SC3904
2SC3905	Si-NPN	Sw,Pow,100V,15A,60W,<300/1800nS	18c	Nec	2SC3762,2SC4131,(BD545C,BD745C)
2SC3906	Si-NPN	120/120V,0,05A,140MHz	?3Sd	Rhm	-
2SC3906K-E	Si-NPN	-	3S	Rhm	→2SC3906K
2SC3906K-R	Si-NPN	-	3S	Rhm	→2SC3906K
2SC3906K-S	Si-NPN	-	3S	Rhm	→2SC3906K
2SC3907	Si-NPN	AF-Pow,180V,12A,130W,30MHz	18j$	Tos	2SC3263,2SC3856
2SC3908	Si-NPN	AM-Pow,50V,25A,Pq=120W(30MHz)	57r*	Mit	-
2SC3909	Si-NPN	Sw,Pow,900/800V,5A,100W,<1000/4500nS	18j$	Sak	BUW11A,BUV82,2SC3153,2SC3232..
2SC391	Si-NPN	VHF/UHF,20V,0,02A,1200MHz	5g	Tos	BF377..378,BF689,BF763,2N2857..
2SC3910	Si-NPN	Sw,Pow,800/500V,15A,150W,<1000/4000nS	77j$	Mat	2SC3993,2SD1313
2SC3912	Si-NPN	-	3S	Sanyo	→2SC3912
2SC3913	Si-NPN	-	3S	Sanyo	→2SC3913
2SC3914	Si-NPN	-	3S	Sanyo	→2SC3914
2SC3915	Si-NPN	-	3S	Sanyo	→2SC3915
2SC3916	Si-NPN-Digital	R1=R2=10kΩ,50V,0,5A,0,3W,250MHz	40c	Sanyo	DTD114ES,RN1224,UN4223,2SC3920
2SC3917	Si-NPN-Digital	Sw,R1=R2=4,7kΩ50V,0,5A,0,3W,250MHz	40c	Sanyo	DTD143ES,RN1223,UN4222,2SC3921
2SC3918	Si-NPN-Digital	Sw,R1=2,2kΩ,R2=10kΩ,50V,0,5A,0,3W,250MHz	40c	Sanyo	DTD123YS,RN1227,UN4224,2SC3922
2SC3919	Si-NPN-Digital	Sw,R1=R2=2,2kΩ,50V,0,5A,0,3W,250MHz	40c	Sanyo	DTD123ES,RN1222,UN4221,2SC3923
2SC392(A)	Si-NPN	VHF/UHF-AGC,30V,0,02A,800(A=>800)MHz	5g	Tos	BF377..378,BF689,BF763,2N2857..
2SC3920	Si-NPN-Digital	=2SC3916:0,6W	7c	Sanyo	→2SC3916
2SC3921	Si-NPN-Digital	=2SC3917:0,6W	7c	Sanyo	→2SC3917
2SC3922	Si-NPN-Digital	=2SC3918:0,6W	7c	Sanyo	→2SC3918
2SC3923	Si-NPN-Digital	=2SC3919:0,6W	7c	Sanyo	→2SC3919
2SC3924	Si-NPN	Sw,Pow,900/800V,3A,30W,<1000/4000nS	15c	Hit	2SC3559,2SC4304,2SC4517,2SC4908..
2SC3925	Si-NPN	Dual,UHF,F-Sw,20V,0,1A,5GHz	-	Sanyo	-
2SC3926	Si-NPN	UHF,20V,0,03A,4GHz	3Sa	Tos	BJQ29,BFQ81,BFR93,BFT75
2SC3927	Si-NPN	Sw,Pow,900/550V,10A,120W,<1000/5500nS	18j$	Sak	BUV47A,BUW12A,2SC3637
2SC3928(A)	Si-NPN	GenP,50(A=60)V,0,1A,200MHz	35a	Mitsubishi	BC846..847,BCW71..72,BCW81..
2SC3928-Q	Si-NPN	-	3S	Mit	→2SC3928

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2SC3928-R	Si-NPN	-	35	Mit	→2SC3928
2SC3928-S	Si-NPN	-	35	Mit	→2SC3928
2SC3928-T	Si-NPN	-	35	Mit	→2SC3928
2SC3929	Si-NPN	-	35(2mm)	Mat	→2SC3929
2SC3929A	Si-NPN	-	35(2mm)	Mat	→2SC3929A
2SC3929A-R	Si-NPN	-	35(2mm)	Mat	→2SC3929A
2SC3929A-S	Si-NPN	-	35(2mm)	Mat	→2SC3929A
2SC3929A-T	Si-NPN	-	35(2mm)	Mat	→2SC3929A
2SC3929-R	Si-NPN	-	35(2mm)	Mat	→2SC3929
2SC3929-S	Si-NPN	-	35(2mm)	Mat	→2SC3929
2SC3929-T	Si-NPN	-	35(2mm)	Mat	→2SC3929
2SC393	Si-NPN	TV-IF,20V,0,02A	5g	Tos	BF198..199,BF224..225,BF505..
2SC3930	Si-NPN	-	35(2mm)	Mat	→2SC3930
2SC3930-A	Si-NPN	-	35(2mm)	Mat	→2SC3930
2SC3930-B	Si-NPN	-	35(2mm)	Mat	→2SC3930
2SC3930-C	Si-NPN	-	35(2mm)	Mat	→2SC3930
2SC3931	SI-NPN	-	35(2mm)	Mat	→2SC3931
2SC3931-B	Si-NPN	-	35(2mm)	Mat	→2SC3931
2SC3931-C	Si-NPN	-	35(2mm)	Mat	→2SC3931
2SC3931-D	Si-NPN	-	35(2mm)	Mat	→2SC3931
2SC3932	Si-NPN	-	35(2mm)	Mat	→2SC3932
2SC3932-S	Si-NPN	-	35(2mm)	Mat	→2SC3932
2SC3932-T	Si-NPN	-	35(2mm)	Mat	→2SC3932
2SC3933	Si-NPN	-	35(2mm)	Mat	→2SC3933
2SC3934	Si-NPN	-	35(2mm)	Mat	→2SC3934
2SC3935	Si-NPN	-	35(2mm)	Mat	→2SC3935
2SC3935-P	Si-NPN	-	35(2mm)	Mat	→2SC3935
2SC3935-Q	Si-NPN	-	35(2mm)	Mat	→2SC3935
2SC3935-R	Si-NPN	-	35(2mm)	Mat	→2SC3935
2SC3936	Si-NPN	-	35(2mm)	Mat	→2SC3936
2SC3936-B	Si-NPN	-	35(2mm)	Mat	→2SC3936
2SC3936-C	Si-NPN	-	35(2mm)	Mat	→2SC3936
2SC3937	Si-NPN	-	35(2mm)	Mat	→2SC3937
2SC3938	Si-NPN	-	35(2mm)	Mat	→2SC3938
2SC3938-Q	Si-NPN	-	35(2mm)	Mat	→2SC3938
2SC3938-R	Si-NPN	-	35(2mm)	Mat	→2SC3938
2SC3938-S	Si-NPN	-	35(2mm)	Mat	→2SC3938
2SC3939	Si-NPN	GenP,80V,0,5A,1W,120MHz	7c(9mm)	Mat	2SC2235,2SD667,2SD1211,2SD1937..
2SC394	Si-NPN	AM/FM-Pre/Mix,35V,0,1A,200MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC3940	Si-NPN	GenP,30V,1A,1W,200MHz	7c(9mm)	Mat	2SC2236,2SC3226,2SD1207,2SD1331..
2SC3940A	Si-NPN	=2SC3940:60V	7c(9mm)	-	2SD863,2SD1014,2SD1146,2SD1207..
2SC3941	Si-NPN	Vid,300/300V,0,07A,1W,80MHz	7c(9mm)	Mat	BF420A,2SC3249,2SC3468..69,2SC4166
2SC3942	Si-NPN	CTV-Chroma,300/300V,0,1A,10W,140MHz	17c	Mat	2SC3565,2SC4075
2SC3943	Si-NPN	=2SC3610:Iso,8W	17c	Mat	(2SC3782)
2SC3944	Si-NPN	AF/HF-Pow,150/150V,1A,15W,200MHz	17c	Mat	2SC3298,2SC3364,2SC4159,2SC4370..
2SC3944A	Si-NPN	=2SC3944:180/180V	17c	-	2SC3298A,B,2SC4159,2SC4883A
2SC3945	Si-NPN	CTV-Vid-Out,300/300V,0,1A,10W,100MHz	17c	Mat	2SC3565,2SC4075,(2SC1505..07,..)
2SC3946	Si-NPN	CTV-Vid-Out,350/300V,0,2A,15W,>50MHz	17c	Mat	(2SC1905)
2SC3947	Si-NPN	Sw,Pow,850/500V,5A,70W,<500/3300nS	18c	Fui	BUW11(A)F,2SC4300,2SC4428,2SC4586
2SC3948	Si-NPN	Sw,Pow,850/500V,10A,75W,<500/3300nS	18c	Fui	2SC4199,(BUV47(A),BUW12(A),2SC3637)
2SC3949	Si-NPN	Sw,Pow,850/500V,15A,80W,<500/3300nS	18c	Fui	BUP23CF,BUV48(A)FI,BUW13(A)F
2SC395	Si-NPN	Sw,20V,0,2A,0,3W,600MHz,20/40nS	2a$	Tos	BSS11..12,BSY17..18,2N2368..69(A),..
2SC3950	Si-NPN	Vid-Dr,Hi-def,30V,0,5A,5W,2000MHz	14b	Sanyo	2SC4821
2SC3951	Si-NPN	Vid-Out,Hi-def,80V,0,3A,8W,600MHz	14b	Sanyo	2SC3954,(2SC3596)
2SC3952	Si-NPN	Vid-Out,Hi-def,80V,0,5A,10W,700MHz	14b	Sanyo	2SC4479,(2SC3597)
2SC3953	Si-NPN	Vid-Out,Hi-def,120V,0,2A,8W,400MHz	14b	Sanyo	2SC3954,(2SC3598)
2SC3954	Si-NPN	Vid-Out,Hi-def,120V,0,3A,8W,400MHz	14b	Sanyo	2SC4565,(2SC3599)
2SC3955	Si-NPN	Vid-Out,Hi-def,200V,0,1A,7W,300MHz	14b	Sanyo	2SC3788,(2SC3600)
2SC3956	Si-NPN	Vid-Out,Hi-def,200V,0,2A,7W,300MHz	14b	Sanyo	2SC4564,(2SC3601,2SC5024)
2SC3957	Si-NPN-Darl	40V,0,3A,100MHz,B>2000	44zg	Hit	-
2SC3957-GIA	SI-N-Darl+Di	-	44	Hit	→2SC3957
2SC3957-GIB	SI-N-Darl+Di	-	44	Hit	→2SC3957
2SC3958	Si-NPN	Sw,Pow,150/60V,5A,30W,<600/3100nS	17j$	Unz	BUW64(A..C),2SC4328,2SD772(A,B)
2SC3959	Si-NPN	=2SC3958:150/80V	17j$	Unz	BUW64(A..C),2SC4328,2SD772(A,B)

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2SC395A	Si-NPN	=2SC395:0,5A,400MHz	2a$	-	BSS10,BSX26,BSX28,BSX39,2N3261
2SC396	Si-NPN	HF/Sw,40V,0,2A,0,3W,450MHz	2a$	Tos	BSS11,BSX19..20,2N2368..69(A)..
2SC3960	Si-NPN	=2SC3958:150/100V	17j$	Unz	BUW64(A..C),2SC4328,2SD772(A,B)
2SC3961	Si-NPN	Sw,Pow,500/400V,5A,40W,<1000/3300nS	17j$	Unz	MJE13070,2SC2535,2SC2827,2SC3830..
2SC3962	Si-NPN	Sw,Pow,500/400V,5A,40W,<500/1900nS	17j$	Unz	MJE13070,2SC2535,2SC2827,2SC3830..
2SC3963	Si-NPN	CTV,AF-Pow,200/160V,0,2A,>50MHz	14b	Tos	2SC3956,2SC4564,2SC4623,(BF415)
2SC3964	Si-NPN	AF-Pow,Hi-beta,40V,2A,220MHz,B>500	14b	Tos	(2SD1694)
2SC3965	Si-NPN	AF,Vid,300/300V,0,1A,1W,140MHz	7c(9mm)	Mat	BF420A,2SC3249,2SC3468..69,2SC4166
2SC3966	Si-NPN	UHF,30V,0,02A,0,2W,1500MHz	25u	Mat	2SC2360,2SC2464,2SC2466,2SC2726..
2SC3967	Si-NPN	-	35	Mat	→2SC3967
2SC3968	Si-NPN	Sw,Pow,400/400V,2A,20W,<1000/3500nS	17j$	Rhm	TIP75C,2SC2333,2SC2738,2SC3169..
2SC3969	Si-NPN	=2SC3968:Iso	17c	Rhm	2SC3309,2SC3560..61,2SC3868,2SC4421
2SC397(D)	Si-NPN	VHF/UHF,20V,0,05A,800(D=>400)MHz	5g	Tos	BF377..378,BF689,BF763,2N2857..
2SC3970	Si-NPN	Sw,Pow,800/500V,1,5A,25W,<1/3,3µS	17c	Mat	BUX84F..85F,2SC3352,2SD1571..
2SC3970A	Si-NPN	=2SC3970:900/500V	17c	-	BUX85F,2SC3794A,2SC3978,2SC4304..
2SC3971	Si-NPN	Sw,Pow,800/500V,3A,30W,<1/3,3µS	17c	Mat	BUT11(A)F,2SC3749,2SC4304,2SD1571,..
2SC3971A	Si-NPN	=2SC3971:900/500V	17c	-	BUT11AF,2SC3559,2SC4304,2SC4517,..
2SC3972	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/3,3µS	17c	Mat	BUT11F,BUT18F,2SC3353,2SC3750..
2SC3972A	Si-NPN	=2SC3972:900/500V	17c	-	BUT11AF,BUT18AF,2SC3795A,2SC4518
2SC3973	Si-NPN	Sw,Pow,800/500V,7A,45W,<1/3,3µS	17c	Mat	BUT12F,BUT22BF,(BUT54,BUT56(A))
2SC3973A	Si-NPN	=2SC3973:900/500V	17c	-	BUT12AF,BUT22CF,(BUT56A)
2SC3974	Si-NPN	Sw,Pow,800/500V,7A,80W,<1/3,3µS	16c	Mat	BUV47FI,BUW12F,2SC4429,2SC4458..
2SC3975	Si-NPN	Sw,Pow,800/500V,10A,100W,<1/3,3µS	16c	Mat	BUW13(A)F,2SC4199,2SC4459,2SC4587,..
2SC3976	Si-NPN	Sw,Pow,800/500V,12A,150W,<1/3,3µS	77j$	Mat	2SC3307,2SC3910,2SC3982
2SC3977	Si-NPN	Sw,Pow,900/800V,1A,30W,<700/2800nS	17c	Mat	BUX85F,2SC3751,2SC3794A,2SC4231..
2SC3977A	Si-NPN	=2SC3977:1000/800V	17c	-	BUX85F,2SC3751,2SC4231,2SC4234..
2SC3978	Si-NPN	Sw,Pow,900/800V,2A,35W,<700/2800nS	17c	Mat	BUX85F,2SC3752,2SC4231,2SC4234..
2SC3978A	Si-NPN	=2SC3978:1000/800V	17c	-	BUX85F,2SC3752,2SC4231,2SC4234..
2SC3979	Si-NPN	Sw,Pow,900/800V,3A,40W,<700/2800nS	17c	Mat	BUT11AF,2SC3752,2SC4234,2SC4304..
2SC3979A	Si-NPN	=2SC3979:1000/800V	17c	-	BUT11AF,2SC3752,2SC4234,2SC4517A
2SC398	Si-NPN	VHF-Pre,20V,0,02A,>250MHz	5g	Tos	BF225,BF310,BF314,BF502,BF507..
2SC3980	Si-NPN	Sw,Pow,900/800V,4A,70W,<700/2800nS	16c	Mat	BUW11AF,2SC4300,2SC4427,2SC4882
2SC3980A	Si-NPN	=2SC3980:1000/800V	16c	-	BUW11AF,2SC4427,2SC4882
2SC3981	Si-NPN	Sw,Pow,900/800V,5A,80W,<700/2800nS	16c	Mat	BUW11AF,2SC4300,2SC4586,2SC4882
2SC3981A	Si-NPN	=2SC3981:1000/800V	16c	-	BUW11AF,2SC4427..28,2SC4584,2SC4882
2SC3982	Si-NPN	Sw,Pow,900/800V,10A,150W,<700/3300nS	77j$	Mat	2SC3307,2SC3992
2SC3983	Si-NPN	GenP,60V,0,15A,0,3W,180MHz	7c	Rhm	BC174,BC182,BC190,BC546,2SD767..
2SC3984	Si-NPN	=2SC3983:	9c	Rhm	BC174,BC182,BC190,BC546,2SD767..
2SC3985	Si-N-Darl+Di	50V,1,2A,15W,180MHz,B=4000	17c	Sanyo	-
2SC3986	Si-N-Darl+Di	50V,2A,15W,180MHz,B=4000	17c	Sanyo	-
2SC3987	Si-N-Darl+Di	50V,3A,15W,180MHz,B=4000	17c	Sanyo	-
2SC3988	Si-NPN	Sw,Pow,800/500V,25A,150W,<500/3300nS	18j$	Sanyo	BUX98P
2SC3989	Si-NPN	Sw,Pow,800/500V,25A,200W,<500/3300nS	77j$	Sanyo	2SD1313
2SC399	Si-NPN	VHF-Mix,20V,0,02A,>250MHz	5g	Tos	BF224,BF503,BF505,BF507,2SC3136+
2SC3990	Si-NPN	Sw,Pow,800/500V,35A,250W,<500/3300nS	77j$	Sanyo	-
2SC3991	Si-NPN	Sw,Pow,800/500V,50A,300W,<500/3300nS	77j$	Sanyo	-
2SC3992	Si-NPN	Sw,Pow,1100/800V,12A,200W,<500/3300nS	77j$	Sanyo	2SC3738,2SC4096
2SC3993	Si-NPN	Sw,Pow,1100/800V,16A,250W,<500/3300nS	77j$	Sanyo	-
2SC3994	Si-NPN	Sw,Pow,1100/800V,25A,300W,<500/3300nS	77j$	Sanyo	-
2SC3995	Si-NPN	HD,Hi-def,1500/800V,12A,180W	77j$	Sanyo	2SC4288A,BU4530AL
2SC3996	Si-NPN	HD,Hi-def,1500/800V,15A,180W	77j$	Sanyo	2SC4289A,BU4530AL
2SC3997	Si-NPN	HD,Hi-def,1500/800V,20A,250W	77j$	Sanyo	2SC4290A,2SC4897,BU4540AL
2SC3998	Si-NPN	HD,Hi-def,1500/800V,25A,250W	77j$	Sanyo	2SC4789,BU4540AL
2SC3999	Si-NPN	Vid-Out,300V,0,1A,0,75W,300MHz	7c	Nec	BF299,BF393,BF420A,2SC3468..
2SC40	Si-NPN	=2SC39:750MHz	2a$	Fui	BF198..199,BF224..225,BF505..
2SC400(D,M)	Si-NPN	GenP,30(D=35)V,0,1A,0,25W,300MHz	2a$	Tos,Mic	BC168,BC183,BC238,BC548,2N3904..
2SC4000	Si-NPN	-	35	Sanyo	→2SC4000
2SC4001	Si-NPN	-	35	Sanyo	→2SC4001
2SC4002	Si-NPN	Sw,Dr,400/400V,0,2A,0,6W,70MHz	7c	Sanyo	MPSA44..45,2SD1350
2SC4003	Si-NPN	-	35	Sanyo	→2SC4003
2SC4004	Si-NPN	Sw,Pow,900/800V,1A,30W,<1/4µS	17c	Mat	BUX85F,2SC3751,2SC3794A,2SC4231..
2SC4005	Si-N-Darl+Di	42V,2A,15W,180MHz,B=4000	17c	Sanyo	-
2SC4006	Si-N-Darl+Di	42V,3A,20W,180MHz,B=4000	17c	Sanyo	-
2SC4007	Si-NPN	AF,Sw-Pow,100V,4A,40W,10MHz	17j$	Rhm	BD243C,BD539C,BD953,2SD726..

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2SC4008	Si-NPN	=2SC4007:Iso,30W	17c	Rhm	2SC3691,2SD1586,(BD243C,BD539C,..)
2SC4009	Si-NPN-Darl	GenP,40V,0,3A,0,3W,200MHz,B=100000	9c	Rhm	BC517,MPSA25..27
2SC401	Si-NPN	GenP,50V,0,1A,0,1W,170MHz,-/650nS	10b	Son	BC167,BC182,BC237,BC547,2SD767..
2SC4010	Si-NPN	=2SC2021M:Pins=14mm	9c	Rhm	→2SC1740
2SC4011	Si-NPN	=2SC2063M:Pins=14mm	9c	Rhm	→2SC2058
2SC4012	Si-NPN	=2SC3078M:Pins=14mm	9c	Rhm	→2SC3078
2SC4013	Si-NPN	=2SC3079M:Pins=14mm	9c	Rhm	→2SC3079
2SC4014	Si-NPN	=2SC3080M:Pins=14mm	9c	Rhm	→2SC3080
2SC4015	Si-NPN	=2SC3269:	9c	Rhm	→2SC3269
2SC4016	Si-NPN	=2SC1652:Pins=14mm,0,4W	9c	Rhm	→2SC1652
2SC4017	Si-NPN-Darl	=2SC1545:Pins=14mm	9c	Rhm	→2SC1545
2SC4018K	Si-NPN	GenP,50V,0,1A,230MHz	35a	Rohm	BC846..847,BCW71..72,BCW81..
2SC4018K-N	Si-NPN	-	35	Rhm	→2SC4018K
2SC4018K-P	Si-NPN	-	35	Rhm	→2SC4018K
2SC4019	Si-NPN	Vid-Pow,300/220V,0,1A,10W,90MHz	30j$	Mit	2SC2924,2SC3408,2SC3805
2SC402(A,B)	Si-NPN	GenP,50V,0,1A,0,1..0,3W,140..170MHz	10b	Son	BC167,BC182,BC237,BC547,2SD767..
2SC4020	Si-NPN	Sw-Reg,900/800V,3A,50W,<1/6µS	17j$	Sak	BUT11A,BUV46A,2SC3150,2SC3490..
2SC4021	Si-NPN	Sw,Pow,1500/800V,3A,100W,-/4,8µS	18j$	Sak	2SC4022,2SD1882
2SC4022	Si-NPN	Sw,Pow,1500/800V,6A,120W,-/4,8µS	18j$	Sak	BU2508A,BUV71,2SC4023
2SC4023	Si-NPN	Sw,Pow,1500/800V,10A,130W,-/4,8µS	18j$	Sak	BU2520A,BUV71
2SC4024	Si-NPN	Hi-beta,Lo-sat,Hi-Ueb,100V,10A,35W	17c	Sak	(2SC4554)
2SC4026	Si-NPN	Sw,Pow,500/400V,5A,35W,<700/2300nS	17c	Mat	2SC3570,2SC3573,2SC4054,2SC4073..
2SC4027	Si-NPN	AF,Sw-Pow,180/160V,1,5A,15W,120MHz	30j$	Sanyo	2SD1033,2SD1080..82,2SD2122..23
2SC4028	Si-NPN	Sw,Pow,1400/800V,10A,100W,<1/5µS	18j$	Tos	BU2520A,BUV71,2SC4023
2SC4029	Si-NPN	AF-Out,230/230V,15A,150W,30MHz	77j$	Tos	-
2SC402S	Si-NPN	=2SC402:80V	10b	-	BCS46,2SC1775(A),2SC2240,2SC3245..
2SC403(A,B,C)	Si-NPN	GenP,50..60V,0,1A,0,1W,140..170MHz	10b	Son	BC174,BC182,BC190,BC546,2SD767..
2SC4030	Si-NPN	Sw,1700/900V,0,05A,1,2W,6MHz	30j$	Sanyo	(2SC4578)
2SC4031	Si-NPN	Sw,2000/900V,0,02A,1,2W,6MHz	30j$	Sanyo	(2SC4579)
2SC4032	Si-NPN-Darl	=2SC1545:Pins=14mm	9c	Rhm	→2SC1545
2SC4033	Si-NPN	GenP,130V,0,03A,0,15W,60MHz	9c	Rhm	2SC2362K,2SC2375,2SC3245A,2SC3800..
2SC4034	Si-NPN	GenP,80V,0,05A,0,15W,140MHz	9c	Rhm	BC546,2SC1890(A),2SC2675,2SD1512..
2SC4035	Si-NPN	=2SC1614:Pins=14mm	9c	Rhm	→2SC1614
2SC4036	Si-NPN	=2SC1615:Pins=14mm	9c	Rhm	→2SC1615
2SC4037	Si-NPN	=2SC1652:Pins=14mm	9c	Rhm	→2SC1652
2SC4038	Si-NPN	=2SC2021:Pins=14mm	9c	Rhm	→2SC1740
2SC4039	Si-NPN	=2SC2063:Pins=14mm	9c	Rhm	→2SC2058
2SC404	Si-NPN	GenP,50V,0,05A,0,1W,170MHz	10b	Son	BC167,BC182,BC237,BC547,2SD767..
2SC4040	Si-NPN	=2SC2673:Pins=14mm	9c	Rhm	→2SC2673
2SC4041	Si-NPN	=2SC3080:Pins=14mm	9c	Rhm	→2SC3080
2SC4042(S)	Si-NPN	UHF,30V,0,05A,0,15W,1500MHz	7c,41c	Rhm	BF377..378,BF357,BF630,2SC2570..
2SC4043(S)	Si-NPN	UHF,20V,0,05A,0,3W,3200MHz	7c,41c	Rhm	2SC2498..99,2SC2570,2SC3776..77
2SC4044	Si-NPN	UHF,30V,0,05A,0,15W,2000MHz	7c	Rhm	BF630,2SC2498..99,2SC2570,2SC3776..77
2SC4045	Si-NPN	UHF,20V,0,05A,0,15W,3200MHz	9c	Rhm	2SC2498..99,2SC2570,2SC3776..77
2SC4046	Si-NPN	AF/HF-Pow,120/120V,0,2A,8W,350MHz	14h$	Hit	2SC3598..99
2SC4047	Si-NPN	-	35	Sanyo	→2SC4047
2SC4048	Si-NPN-Digital	Sw,50V,0,1A,0,2W,R1=10kΩ,R2=47kΩ	40c	Sanyo	AA1A4P,DTC114YS,RN1007,UN4214..
2SC4049	Si-NPN-Digital	=2SC4048:	40f	Sanyo	→2SC4048
2SC405	Ge-NPN	Sw,25V,0,2A,0,15W,B=60	2a	Mit	ASY28..29,ASY73..75
2SC4050	Si-NPN	AF,120/120V,0,1A,310MHz	35a	Hit	2SC1622A,2SC3324
2SC4050-D	Si-NPN	-	35	Hit	→2SC4050
2SC4050-E	Si-NPN	-	35	Hit	→2SC4050
2SC4051	Si-NPN	Sw,Pow,600/450V,3A,40W,<500/2200nS	17j$	Shi	BUJ202A,BUT11,BUT93,BUV46,2SC3086...
2SC4052	Si-NPN	Sw,Pow,600/450V,3A,25W,20MHz	15c	Shi	2SC4054,2SC4304,2SD1571,BUJ202AX,BUT11F...
2SC4053	Si-NPN	Sw,Pow,600/450V,5A,50W,<500/2200nS	17j$	Shi	2SC3047,2SC3087,BUJ204A,BUT11,MJE13070...
2SC4054	Si-NPN	=2SC4053:Iso	15c	Shi	BUT11F,2SC3750,2SC3795,2SC4056..
2SC4055	Si-NPN	Sw,Pow,600/450V,8A,60W,<500/2200nS	17j$	Shi	BUJ205A,BUT54,BUT56(A),MJE13006..07...
2SC4056	Si-NPN	=2SC4055:Iso,45W	15c	Shi	BU306F,BUJ205AX,BUT12F,BUT22BF,2SC4546..
2SC4057	Si-NPN	=2SC4055:80W	16j$	Shi	BUP22A,2SC3831,2SC4058,2SC4157..
2SC4058	Si-NPN	Sw,Pow,600/450V,10A,100W,<500/2200nS	16j$	Shi	BUP23A,2SC3450,2SC3831,2SC4157..
2SC4059	Si-NPN	Sw,Pow,600/450V,15A,130W,<500/2200nS	16j$	Shi	BUP23A,BUW13(A),2SC3451,2SC3638..
2SC406	Ge-NPN	=2SC405:B=120	2a	Mit	ASY28..29,ASY73..75
2SC4060	Si-NPN	Sw,Pow,600/450V,20A,150W,<500/2200nS	16j$	Shi	BUX98AP,2SC3988
2SC4061K	Si-NPN	Vid,300/300V,0,1A,100MHz	35a	Rhm	BFN26

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2SC4061K-M	Si-NPN	-	35	Rhm	→2SC4061K
2SC4061K-N	Si-NPN	-	35	Rhm	→2SC4061K
2SC4061K-P	Si-NPN	-	35	Rhm	→2SC4061K
2SC4062	Si-NPN+Diode	Hi-beta, 100V, ±7A, 30W, 100MHz, B>450	17c	Nec	2SC4553
2SC4063	Si-NPN+Diode	Hi-beta, 100V, 15A, 35W, 100MHz, B>450	17c	Nec	2SC4554
2SC4064	Si-NPN	Lo-sat, 50V, 12A, 35W, 40MHz	17c	Sak	2SC3709..10, 2SD1669, (2SD1062)
2SC4065	Si-NPN+Diode	=2SC4064: 60V, ±12A	17c	Sak	2SC3709..10, 2SD1669, (2SD1062)
2SC4066	Si-NPN	-	35	Sanyo	→2SC4066
2SC4067	Si-NPN-Digital	Sw, 50V, 0,1A, 0,3W, 250MHz, R2=47kΩ	40c	Sanyo	DTC144GS
2SC4068	Si-NPN	-	35(2mm)	Mat	→2SC4068
2SC4069	Si-NPN	-	35	Sanyo	→2SC4069
2SC407	Si-NPN	Sw, Pow, 150/100V, 10A, 100W, B>10	23a$	Shi	BUV21, BUW70, BUX17(A..C), BUY18, 2SC2944,..
2SC4070	Si-NPN-Digital	Sw, 50V, 0,1A, 0,3W, 250MHz, R2=22kΩ	40c	Sanyo	DTC124GS
2SC4071	Si-NPN	Dual, 30V, 0,03A, 0,25W, 1200MHz	-	Sanyo	-
2SC4072	Si-NPN	Dual, 25V, 0,05A, 0,25W, 3500MHz	-	Sanyo	-
2SC4073	Si-NPN	Sw-Reg, 500/400V, 5A, 30W, <1/3,5µS	17c	Sak	2SC3570, 2SC3573, 2SC4054, 2SC4417..
2SC4074	Si-NPN	VHF/UHF, 30V, 0,05A, 1500MHz	35a	Rohm	BFR53, 2SC3014, 2SC3016, 2SC3773
2SC4075	Si-NPN	CTV-AF/Vid, 300/300V, 0,2A, 10W, >50MHz	17c	Sanyo	2SC3565, (2SC1505..07, 2SC1755..57,..)
2SC4076	Si-NPN	GenP, 60V, 0,15A, 180MHz	35a	Rohm	BC846, BCV71..72, 2SC3323, 2SC4050
2SC4077	Si-NPN	AF, LN, 30V, 0,1A, 0,3W, 230MHz	7c	Rhm	BC169, BC184, BC239, BC549, 2SC2240+
2SC4078	Si-NPN	=2SC4077:	9c	Rhm	→2SC4077
2SC4079	Si-NPN	=2SC4077: SMD	35a	Rhm	BC849..850, BCF32..33, BCF81..
2SC408	Si-NPN	=2SC407: B>20	23a$	Shi	BUV21, BUW70, BUX17(A..C), BUY18, 2SC2944,..
2SC4080	Si-NPN	Vid, 200/200V, 0,1A, 400MHz	39b	Sanyo	BFN16, BFN18, 2SC3380, 2SC3515
2SC4082	Si-NPN	=2SC3837K:	35a(2mm)	Rhm	BFS17W, BFS47W, BFS17W, 2SC4780
2SC4082-L	Si-NPN	-	35(2mm)	Rhm	→2SC4082
2SC4082-M	Si-NPN	-	35(2mm)	Rhm	→2SC4082
2SC4082-N	Si-NPN	-	35(2mm)	Rhm	→2SC4082
2SC4082-P	Si-NPN	-	35(2mm)	Rhm	→2SC4082
2SC4082-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4082
2SC4083	Si-NPN	SI-N 11V 3.2GHz TV tuners	-	Rhm	-
2SC4083-M	Si-NPN	-	35(2mm)	Rhm	→2SC4083
2SC4083-N	Si-NPN	-	35(2mm)	Rhm	→2SC4083
2SC4083-P	Si-NPN	-	35(2mm)	Rhm	→2SC4083
2SC4083-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4083
2SC4084-L	Si-NPN	-	35(2mm)	Rhm	→2SC4084
2SC4084-M	Si-NPN	-	35(2mm)	Rhm	→2SC4084
2SC4084-N	Si-NPN	-	35(2mm)	Rhm	→2SC4084
2SC4084-P	Si-NPN	-	35(2mm)	Rhm	→2SC4084
2SC4084-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4084
2SC4085	Si-NPN	VHF/UHF, 30V, 0,02A, 1000MHz	44zf	Nec	2SC4086..4087
2SC4086	Si-NPN	UHF, 30V, 0,05A, 2000MHz	44zf	Nec	2SC4087
2SC4087	Si-NPN	UHF, 30V, 0,05A, 2000MHz	44zf	Nec	2SC4086
2SC4088	Si-NPN	UHF, 15V, 5mA, 4000MHz	44zf	Nec	2SC4089
2SC4089	Si-NPN	UHF, 25V, 0,03A, 4000MHz	44zf	Nec	-
2SC4085-L	Si-NPN	-	35(2mm)	Rhm	→2SC4083
2SC409	Si-NPN	=2SC407: 200/140V	23a$	Shi	BUV21, BUX17(A..C), BUX42, BUY18, 2SC2944,..
2SC4090	Si-NPN	UHF, 30V, 0,05A, 2000MHz	44ze	Nec	2SC4092
2SC4091	Si-NPN	UHF, 15V, 5mA, 4GHz	44ze	Nec	2SC4092
2SC4092	Si-NPN	UHF, 25V, 0,07A, 6GHz, B=100-200	44ze	Nec	-
2SC4092	Si-NPN	UHF, 25V, 0,07A, 6GHz, B=40-120	44ze	Nec	-
2SC4092-R4	Si-NPN	-	44	Nec	→2SC4092
2SC4092-R5	Si-NPN	-	44	Nec	→2SC4092
2SC4093	Si-NPN	UHF, 20V, 0,1A, 6500MHz	44ze	Nec	-
2SC4093-R26	Si-NPN	-	44	Nec	→2SC4093
2SC4093-R27	Si-NPN	-	44	Nec	→2SC4093
2SC4093-R28	Si-NPN	-	44	Nec	→2SC4093
2SC4094	Si-NPN	UHF, 20V, 0,065A, 9000MHz	44ze	Nec	-
2SC4094-R36	Si-NPN	-	44	Nec	→2SC4094
2SC4094-R37	Si-NPN	-	44	Nec	→2SC4094
2SC4094-R38	Si-NPN	-	44	Nec	→2SC4094
2SC4095	Si-NPN	UHF, 20V, 0,035A, 10GHz	44ze	Nec	-
2SC4095-Q	Si-NPN	npn fT 10GHz	-	Nec	-
2SC4095-R	Si-NPN	npn fT 10GHz	-	Nec	-

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2SC4095-R46	Si-NPN	-	44	Nec	→2SC4095
2SC4095-R47	Si-NPN	-	44	Nec	→2SC4095
2SC4095-R48	Si-NPN	-	44	Nec	→2SC4095
2SC4095-S	Si-NPN	npn fT10GHz	-	Nec	-
2SC4096	Si-NPN	Sw,Pow,1400/800V,10A,150W,1/3,8µS	77j$	Mat	2SC3995,2SC4111
2SC4097	Tr		-	Rohm	-
2SC4097-P	Si-NPN	-	35(2mm)	Rhm	→2SC4097
2SC4097-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4097
2SC4097-R	Si-NPN	-	35(2mm)	Rhm	→2SC4097
2SC4098	Tr		-	Rohm	-
2SC4098-N	Si-NPN	-	35(2mm)	Rhm	→2SC4098
2SC4098-P	Si-NPN	-	35(2mm)	Rhm	→2SC4098
2SC4098-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4098
2SC4099	Si-NPN	=2SC2059K:	35a(2mm)	Rhm	2SC3931,2SC3935,2SC5020
2SC4099-M	Si-NPN	-	35(2mm)	Rhm	→2SC4099
2SC4099-N	Si-NPN	-	35(2mm)	Rhm	→2SC4099
2SC4099-P	Si-NPN	-	35(2mm)	Rhm	→2SC4099
2SC41	Si-NPN	Sw,Pow,150V,5A,50W,20MHz,B>12	23a$	Sony	BD245D,2N3442,2SC2260..2262,2SD731..
2SC410(A)	Si-NPN	=2SC407:200/140(A=200/200)V,B>20	23a$	Shi	BUX17(A..C),BUX42,BUY18,2SC2944,..
2SC4100	Si-NPN	=2SC3082K:	35a(2mm)	Rhm	BF547W,BF517W,BFS17,2SC4780
2SC4100-M	Si-NPN	-	35(2mm)	Rhm	→2SC4100
2SC4100-N	Si-NPN	-	35(2mm)	Rhm	→2SC4100
2SC4100-P	Si-NPN	-	35(2mm)	Rhm	→2SC4100
2SC4100-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4100
2SC4101	Si-NPN	AF,LN,120V,0,05A,140MHz	35a(2mm)	Rhm	2SC4117,2SC4180,2SD1821
2SC4102	Tr		-	Rohm	-
2SC4102-E	Si-NPN	-	35(2mm)	Rhm	→2SC4102
2SC4102-R	Si-NPN	-	35(2mm)	Rhm	→2SC4102
2SC4102-S	Si-NPN	-	35(2mm)	Rhm	→2SC4102
2SC4103	Si-NPN	=2SC3802K:	35a(2mm)	Rhm	BF517W,BF547W,BFS17,2SC4780
2SC4103-M	Si-NPN	-	35(2mm)	Rhm	→2SC4103
2SC4103-N	Si-NPN	-	35(2mm)	Rhm	→2SC4103
2SC4103-P	Si-NPN	-	35(2mm)	Rhm	→2SC4103
2SC4103-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4103
2SC4104	Si-NPN	Vid,70V,0,05A,700MHz	35a	Sanyo	-
2SC4105	Si-NPN	Sw,Pow,500/400V,4A,40W,<500/2800nS	17j$	Sanyo	BUT93,TIP75C,2SC3038,2SC4051..
2SC4106	Si-NPN	Sw,Pow,500/400V,7A,50W,<500/2800nS	17j$	Sanyo	MJE13006,2SC3170,2SC4055,2SC4055..
2SC4107	Si-NPN	Sw,Pow,500/400V,10A,60W,<500/2800nS	17j$	Sanyo	BUT76,MJE13008,2SC3562,2SC4164..
2SC4108	Si-NPN	Sw,Pow,500/400V,12A,100W,<500/2800nS	18j$	Sanyo	BUP23,2SC3520,2SC4139,2SC4434..
2SC4109	Si-NPN	Sw,Pow,500/400V,16A,140W,<500/2800nS	18j$	Sanyo	BUX98(A)P,2SC3850,2SC4140
2SC411	Si-NPN	=2SC407:300/200V	23a$	Shi	BUX17A..C,BUX42,BUY18,2N6547,2SC2626,..
2SC4110	Si-NPN	Sw,Pow,500/400V,25A,160W,<500/2800nS	18j$	Sanyo	BUX98P
2SC4111	Si-NPN	Sw,Pow,1500/700V,10A,150W,<1/12,6µS	77j$	Mat	2SC3995
2SC4112	Si-NPN	-	3S	Sanyo	→2SC4112
2SC4113	Si-NPN-Digital	Sw,50V,0,1A,200MHz,R1=2,2kΩ	40c	Sanyo	-
2SC4114	Si-NPN	600/550V,0,1A,<2/5,5µS	39b	Mat	-
2SC4115(A,S)	Si-NPN	AF,Sw,40V,3A,0,3W,290MHz	41c	Rhm	2SD1347,2SD1507,2SD1617,2SD2152..
2SC4116	Si-NPN	GenP,LN,60V,0,15A,>80MHz	35a(2mm)	Toshiba	BC846W,2SC4141,2SC4177,2SD1819A
2SC4116-BL	Si-NPN	-	35(2mm)	Tos	→2SC4116
2SC4116-GR	Si-NPN	-	35(2mm)	Tos	→2SC4116
2SC4116-O	Si-NPN	-	35(2mm)	Tos	→2SC4116
2SC4116-Y	Si-NPN	-	35(2mm)	Tos	→2SC4116
2SC4117	Si-NPN	GenP,LN,120V,0,1A,100MHz	35a(2mm)	Toshiba	2SC4101..4102,2SC4180
2SC4117-BL	Si-NPN	-	35(2mm)	Tos	→2SC4117
2SC4117-GR	Si-NPN	-	35(2mm)	Tos	→2SC4117
2SC4118	Si-NPN	GenP,35V,0,5A,300MHz	35a(2mm)	Toshiba	BC817W,2SC4097,2SD1820A,2SD1949
2SC4118-O	Si-PNP	-	35(2mm)	Tos	→2SC4118
2SC4118-Y	Si-PNP	-	35(2mm)	Tos	→2SC4118
2SC4119	Si-N-Darl+Di	Sw,Pow,1500/800V,15A,250W,B>25	77j$	Sanyo	-
2SC412	Si-NPN	=2SC407:300/200V,B>20	23a$	Shi	BUX17A..C,BUX42,BUY18,2N6547,2SC2626,..
2SC4120	Si-NPN-Digital	=2SC4121:SMD	35a	Sanyo	FA1F4Z,DTC124TK,KSR1111,UN2217
2SC4121	Si-NPN-Digital	Sw,50V,0,1A,0,3W,250MHz,R1=22kΩ	40c	Sanyo	AA1F4Z,DTC124TS,KSR1011,UN4217
2SC4122	Si-NPN+Diode	HD,Hi-def,1500/800V,6A,60W	18c	Sanyo	2SC4294,2SC4764,BU4507DX
2SC4123	Si-NPN+Diode	HD,Hi-def,1500/800V,7A,60W	18c	Sanyo	2SC3892A,2SC4762,2SC4916,BU4508DX

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2SC4124	Si-NPN+Diode	HD,Hi-def,1500/800V,8A,70W	18c	Sanyo	2SC3892,2SC4763,BU4522DX
2SC4125	Si-NPN+Diode	HD,Hi-def,1500/800V,10A,70W	18c	Sanyo	BU2520DF
2SC4126	Si-NPN	UHF,15V,0,05A,6GHz	44ze	Hit	2SC4092
2SC4127	Si-NPN	UHF,15V,0,05A,7,5GHz	44ze	Hit	2SC4094
2SC4128	Si-NPN	GenP,50V,0,1A,230MHz	35a(2mm)	Rohm	2SC4081,2SC4141
2SC4128-N	Si-NPN	-	35(2mm)	Mat	→2SC4128
2SC4128-P	Si-NPN	-	35(2mm)	Mat	→2SC4128
2SC4129	Si-NPN	Sw,Pow,400/400V,5A,30W,<1/3,5µS	17c	Rhm	2SC3570,2SC3573,2SC4073,2SC4418..
2SC413	Si-NPN	HF/Sw-Pow,60V,1,5A,20W,180MHz	2a$	Oki	(BD137,BD228,BD377,2SD1177..1178)
2SC4130	Si-NPN	Sw,Pow,500/400V,7A,30W,<1/2,7µS	17c	Sak	2SC3571,2SC3574,2SC3890,2SC4056..
2SC4131	Si-NPN	Hi-Ueb,100V,15A,60W,0,5/2,4µS	18c	Sak	-
2SC4132	Si-NPN	Sw,120V,2A,80MHz	39b	Rhm	2SC3649,2SD1420..1421
2SC4132-N	Si-NPN	-	39	Rhm	→2SC4132
2SC4132-P	Si-NPN	-	39	Rhm	→2SC4132
2SC4132-Q	Si-NPN	-	39	Rhm	→2SC4132
2SC4132-R	Si-NPN	-	39	Rhm	→2SC4132
2SC4133	Si-NPN-Digital	Sw,50V,0,1A,250MHz,R1=4,7kΩR2=47kΩ	40c	Sanyo	DTC143ZS,KSR1014,RN1006,2SC4195
2SC4134	Si-NPN	Sw,Pow,120V,1A,10W,120MHz	30j$	Sanyo	2SD1074..75,2SD1283..84
2SC4135	Si-NPN	Sw,Pow,120V,2A,15W,120MHz	30j$	Sanyo	2SD1815..16
2SC4136	Si-NPN	Sw,Pow,200/120V,20A,140W,<0,5/2µS	23a$	Fujitsu	BUV11,BUW58,BUX11,2SC2865(A)..
2SC4137	Si-NPN	Hi-beta,25V,0,1A,400MHz,B>560	14b	Rhm	-
2SC4138	Si-NPN	Sw-Reg,500/400V,10A,80W,<1/3,5µS	18j$	Sak	BUP23,2SC3042,2SC4058,2SC4157..
2SC4139	Si-NPN	Sw-Reg,500/400V,15A,120W,<1/3,5µS	18j$	Sak	BUP23,2SC3435,2SC3520,2SC4434..
2SC414	Si-NPN	HF/Sw-Pow,90V,1,5A,20W,180MHz	2a$	Oki	(BD139,BD230,BD379,2SD1177..1178)
2SC4140	Si-NPN	Sw-Reg,500/400V,18A,130W,<1/3,5µS	18j$	Sak	BUX98AP,2SC3850,2SC4060,2SC4110..
2SC4141	Si-NPN	GenP,60V,0,1A,180MHz	35a(2mm)	Rohm	BC846W,2SC4116,2SC4177,2SD1819A..
2SC4142	Si-NPN	TV-HD,1500/800V,5A,50W	18c	Hit	BU706F,2SD1545..46,2SD1655..56..
2SC4143	Si-NPN	TV-HD,1500/800V,5A,50W	18c	Hit	BU706F,2SD1545..46,2SD1655..56..
2SC4144	Si-NPN	TV-HD,1300/500V,8A,50W	18c	Hit	BU2508AF,BU908F,2SC3886,2SD1548..
2SC4145	Si-NPN	AF,Sw,80V,2A,1,2W,<1/4µS	7c(9mm)	Rhm	2SC3328,2SC3669,2SD1015,2SD2182
2SC4146	Si-NPN	-	35	Sanyo	→2SC4146
2SC4147	Si-NPN	HF/Vid-Pow,300/300V,0,1A,5W,100MHz	?14h($)	Rhm	BF417,BF459,2SC3417,2SC3503..
2SC4148	Si-NPN	Sw,Pow,Lo-sat,60V,7A,25W,<300/2000nS	15c	Shi	2SC3692,2SC3747,2SC4550
2SC4149	Si-NPN	Sw,Pow,Lo-sat,60V,10A,25W,<300/2000nS	15c	Shi	2SC3693,2SC3748,2SC4551
2SC415	Si-NPN	HF/Sw-Pow,120V,1,5A,20W,180MHz	2a$	Oki	(2SC2690(A),2SC3117,2SD669)
2SC4150	Si-NPN	Sw,Pow,Lo-sat,60V,12A,25W,<300/2000nS	15c	Shi	2SC3709..10,2SC4065,2SC4595
2SC4151	Si-NPN	Sw,Pow,Lo-sat,60V,15A,30W,<300/2000nS	15c	Shi	2SC3694,2SC4552
2SC4152	Si-NPN	Sw,Pow,1400/700V,0,3A,20W,<2/4µS	17c	Mat	2SC4631
2SC4153	Si-NPN	Sw,Pow,200/120V,7A,30W,<0,5/3,5µS	17c	Sak	2SD1792
2SC4154	Si-NPN	=2SC2320:	35a(2mm)	Mit	2SC4116
2SC4154-E	Si-NPN	-	35(2mm)	Mit	→2SC4154
2SC4154-F	Si-NPN	-	35(2mm)	Mit	→2SC4154
2SC4154-G	Si-NPN	-	35(2mm)	Mit	→2SC4154
2SC4155	Si-NPN	=2SC3928:	35a(2mm)	Mit	BC847W,2SC4081,2SC4128,2SC4141..
2SC4155-Q	Si-NPN	-	35(2mm)	Mit	→2SC4155
2SC4155-R	Si-NPN	-	35(2mm)	Mit	→2SC4155
2SC4155-S	Si-NPN	-	35(2mm)	Mit	→2SC4155
2SC4155-T	Si-NPN	-	35(2mm)	Mit	→2SC4155
2SC4156	Si-NPN	Dual,60V,0,5A,0,4W,300MHz	-	Sanyo	-
2SC4157	Si-NPN	Sw,Pow,600/450V,10A,100W,<0,5/3µS	18j$	Tos	BUP23,2SC3450,2SC3831,2SC4058..
2SC4158	Si-NPN	Vid-Out,250/250V,0,1A,300MHz,8W	17c	Mat	2SC3565,2SC4075,(2SC1505..1507,..)
2SC4159	Si-NPN	AF,Sw-Pow,180/160V,1,5A,15W,100MHz	17c	Sanyo	2SC3298A,B,2SC4883A
2SC416	Si-NPN	HF/Sw-Pow,90V,1,5A,20W,180MHz	2a$	Oki	(BD139,BD230,BD379,2SD1177..1178)
2SC4160	Si-NPN	=2SC4105:Iso,25W	17c	Sanyo	2SC3573,2SC4054,2SC4073,2SC4418..
2SC4161	Si-NPN	=2SC4106:Iso,30W	17c	Sanyo	2SC3571,2SC3574,2SC4056,2SC4130..
2SC4162	Si-NPN	=2SC4107:Iso,35W	17c	Sanyo	2SC3562,2SC3572,2SC3575,2SD1795..
2SC4163	Si-NPN	=2SC4108:Iso,40W	17c	Sanyo	-
2SC4164	Si-NPN	=2SC4108:70W	17j$	Sanyo	BUV66(A),MJE13008..13009
2SC4165	Si-NPN	HF/Vid-Pow,300/300V,0,2A,130MHz	14h$	Hit	BF417,2SC2621,(BF617,BF758..759)
2SC4166	Si-NPN	Sw,Vid,400/400V,0,1A,0,9W,20MHz	7c(9mm)	Rhm	2SC3469
2SC4167	Si-NPN	UHF-Pow,35V,2A,Pq=8W(520MHz)	-	Mit	-
2SC4168	Si-NPN	Sw,40V,0,15A,<40/205nS	35a	Sanyo	-
2SC4169	Si-N-Darl+Di	+Z-Di(B→C),Sw,50V,1,2A,1W,B=4000	7c(9mm)	Sanyo	2SD1153,2SD1809,2SD1929,2SD2026
2SC417..419	Si-NPN	-		Oki	-

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2SC4170	Si-NPN	Dual-Emitter, 50V, 0,2A, 180MHz	44	Sanyo	-
2SC4171	Si-NPN	Sw, Pow, 800/500V, 3A, 40W, <1/4µS	30j$	Sanyo	2SC4221, 2SC4599, (BUT11(A), 2SC3086, +)
2SC4172	Si-NPN	Sw, Pow, 800/500V, 5A, 50W, <1/4µS	30j$	Sanyo	2SC4222, 2SC4600, (BUT11(A), 2SC3047, +)
2SC4173	Si-NPN	Sw, 60V, 0,5A, 30/150nS	35a(2mm)	NEC	2SD1820A
2SC4173-B12	Si-NPN	-	35(2mm)	Nec	→2SC4173
2SC4173-B13	Si-NPN	-	35(2mm)	Nec	→2SC4173
2SC4173-B14	Si-NPN	-	35(2mm)	Nec	→2SC4173
2SC4174	Si-NPN	HF/AF, 180/160V, 0,05A, 120MHz	35a(2mm)	Nec	BF820W, BF822W
2SC4175	Si-NPN	Sw, 40V, 0,2A, <20/40nS	35a(2mm)	NEC	2SC4176
2SC4175-B2	Si-NPN	-	35(2mm)	Nec	→2SC4175
2SC4175-B3	Si-NPN	-	35(2mm)	Nec	→2SC4175
2SC4175-B4	Si-NPN	-	35(2mm)	Nec	→2SC4175
2SC4176	Si-NPN	Sw, 40V, 0,2A, <12/18nS	35a(2mm)	Nec	-
2SC4176-B33	Si-NPN	-	35(2mm)	Nec	→2SC4176
2SC4176-B34	Si-NPN	-	35(2mm)	Nec	→2SC4176
2SC4176-B35	Si-NPN	-	35(2mm)	Nec	→2SC4176
2SC4177	Si-NPN	GenP, 60V, 0,1A, 250MHz	35a(2mm)	Nec	2SC4141
2SC4177-L4	Si-NPN	-	35(2mm)	Nec	→2SC4177
2SC4177-L5	Si-NPN	-	35(2mm)	Nec	→2SC4177
2SC4177-L6	Si-NPN	-	35(2mm)	Nec	→2SC4177
2SC4177-L7	Si-NPN	-	35(2mm)	Nec	→2SC4177
2SC4178	Si-NPN	FM, 30V, 0,02A, 600MHz	35a(2mm)	NEC	2SC3932, 2SC3935
2SC4178-F12	Si-NPN	-	35(2mm)	Nec	→2SC4178
2SC4178-F13	Si-NPN	-	35(2mm)	Nec	→2SC4178
2SC4178-F14	Si-NPN	-	35(2mm)	Nec	→2SC4178
2SC4179	Si-NPN	AM/FM, 50V, 0,05A, >150MHz	35a(2mm)	Nec	2SC3931, 2SC3936
2SC4179-FA3	Si-NPN	-	35(2mm)	Nec	→2SC4179
2SC4179-FA4	Si-NPN	-	35(2mm)	Nec	→2SC4179
2SC4180	Si-NPN	GenP, 120V, 0,05A, >50MHz	35a(2mm)	Nec	2SC4101..4102, 2SC4117
2SC4180-D15	Si-NPN	-	35(2mm)	Nec	→2SC4180
2SC4180-D16	Si-NPN	-	35(2mm)	Nec	→2SC4180
2SC4180-D17	Si-NPN	-	35(2mm)	Nec	→2SC4180
2SC4180-D18	Si-NPN	-	35(2mm)	Nec	→2SC4180
2SC4181(A)	Si-NPN	Hi-beta, Hi-Ueb, 60V, 0,15A, B>1000	35a(2mm)	NEC	-
2SC4181A-L15	Si-NPN	-	35(2mm)	Nec	→2SC4181A
2SC4181A-L16	Si-NPN	-	35(2mm)	Nec	→2SC4181A
2SC4181-L17	Si-NPN	-	35(2mm)	Nec	→2SC4181
2SC4181-L18	Si-NPN	-	35(2mm)	Nec	→2SC4181
2SC4182	Si-NPN	VHF-Mix/Osc, 30V, 0,05A, 1100MHz, B=120-220	35a(2mm)	Nec	-
2SC4182	Si-NPN	VHF-Mix/Osc, 30V, 0,05A, 1100MHz, B=60-105	35a(2mm)	Nec	-
2SC4182	Si-NPN	VHF-Mix/Osc, 30V, 0,05A, 1100MHz, B=85-150	35a(2mm)	Nec	-
2SC4182-T32	Si-NPN	-	35(2mm)	Nec	→2SC4182
2SC4182-T33	Si-NPN	-	35(2mm)	Nec	→2SC4182
2SC4182-T34	Si-NPN	-	35(2mm)	Nec	→2SC4182
2SC4183	Si-NPN	VHF-V/M, 30V, 0,02A, 1000MHz, B=120-240	35a(2mm)	Nec	-
2SC4183	Si-NPN	VHF-V/M, 30V, 0,02A, 1000MHz, B=60-120	35a(2mm)	Nec	-
2SC4183	Si-NPN	VHF-V/M, 30V, 0,02A, 1000MHz, B=90-180	35a(2mm)	Nec	-
2SC4183-U16	Si-NPN	-	35(2mm)	Nec	→2SC4183
2SC4183-U17	Si-NPN	-	35(2mm)	Nec	→2SC4183
2SC4183-U18	Si-NPN	-	35(2mm)	Nec	→2SC4183
2SC4184	Si-NPN	UHF-Mix, 30V, 0,05A, 1800MHz, B=100-200	35a(2mm)	Nec	-
2SC4184	Si-NPN	UHF-Mix, 30V, 0,05A, 1800MHz, B=40-80	35a(2mm)	Nec	-
2SC4184	Si-NPN	UHF-Mix, 30V, 0,05A, 1800MHz, B=60-120	35a(2mm)	Nec	-
2SC4184-T42	Si-NPN	-	35(2mm)	Nec	→2SC4184
2SC4184-T43	Si-NPN	-	35(2mm)	Nec	→2SC4184
2SC4184-T44	Si-NPN	-	35(2mm)	Nec	→2SC4184
2SC4185-U21	Si-NPN	UHF-Mix/Osc, 30V, 0,05A, 2000MHz, B=40..80	35a(2mm)	Nec	-
2SC4185-U22	Si-NPN	UHF-Mix/Osc, 30V, 0,05A, 2000MHz, B=60..120	35a(2mm)	Nec	-
2SC4185-U23	Si-NPN	UHF-Mix/Osc, 30V, 0,05A, 2000MHz, B=90..80	35a(2mm)	Nec	-
2SC4186-T62	Si-NPN	UHF-Mix, 25V, 0,03A, 4000MHz, B=40..80	35a(2mm)	Nec	-
2SC4186-T63	Si-NPN	UHF-Mix, 25V, 0,03A, 4000MHz, B=60..120	35a(2mm)	Nec	-
2SC4186-T64	Si-NPN	UHF-Mix, 25V, 0,03A, 4000MHz, B=100..200	35a(2mm)	Nec	-
2SC4187-R6A	Si-NPN	UHF, 15V, 5mA, 4000MHz, B=50..100	35a(2mm)	Nec	BFR92W, BFR280W
2SC4187-R6B	Si-NPN	UHF, 15V, 5mA, 4000MHz, B=80..160	35a(2mm)	Nec	BFR92W, BFR280W

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2SC4187-R6C	Si-NPN	UHF,15V,5mA,4000MHz,B=125..250	35a(2mm)	Nec	BFR92W,BFR280W
2SC4188	Si-NPN	Vid-Out,Hi-def,200V,0,1A,10W,150MHz	17j$	Sanyo	2SC3782
2SC4189	Si-NPN	Vid,300/300V,0,1A,100MHz	39b	Rhm	BFN18,2SC3380,2SC3515,2SC3554
2SC4190	Si-NPN	65V,0,3A,>1500MHz	17c	Mat	-
2SC4191	Si-NPN	Sw,Pow,500/400V,2A,20W,<1/3,5µS	17j$	old	BUX84..85,TIP75C,2SC2738,2SC3169,..
2SC4192	Si-NPN	Sw,Pow,500/400V,3A,30W,<1/3,5µS	17j$	old	BUT93,TIP75C,2SC2535,2SC4105..
2SC4193	Si-NPN	Sw,Pow,500/400V,5A,40W,<1/3,5µS	17j$	old	MJE13070,2SC2535,2SC2827,2SC5C3830..
2SC4194	Si-NPN	Sw,Pow,500/400V,7A,50W,<1/3,5µS	17j$	old	MJE13006,2SC3170,2SC4055,2SC4106..
2SC4195	Si-NPN-Digital	=2SC4133:	40f	Sanyo	→2SC4133
2SC4196	Si-NPN	UHF-Osc,25V,0,05A,2400MHz	35a	Hit	BFT75,2SC3014,2SC3772..3773
2SC4197	Si-NPN	UHF-V/M,25V,0,05A,3800MHz	35a	Hit	BF770A,BFT75,2SC2845,2SC3774
2SC4198	Si-NPN	Hi-beta,25V,0,5A,200MHz,B=820	14b	Rhm	-
2SC4199	Si-NPN	TV-HD/SMPS,1400/800V,10A,100W	18c	Sak	BU2520AF,2SC3897,2SC4542,2SD1548..
2SC4199A	Si-NPN	=2SC4199:1500/800V	18c	-	BU2520AF,2SC3897,2SC4542,2SC5068..
2SC42	Si-NPN	=2SC41:B>4	23a$	Son	BD245D,2N3442,2SC2260..2262,2SD731..
2SC420	Si-NPN	Dual,25V,0,08A,0,15W,<15/30nS	81bt	Oki	-
2SC4200	Si-NPN	Sw,Vid-Out,20V,0,6A,5W,2500MHz	14b	Tos	-
2SC4201	Si-NPN	Sw,Vid-Out,100V,0,5A,30W,1100MHz	17l&	Tos	(2SC4411)
2SC4202	Si-NPN	=2SC4201:20W	17j$	Tos	2SC4411
2SC4203(LB)	Si-NPN	Sw,Pow,Vid-Out,Hi-res,180V,0,5A,10W,400MHz	30j$	Tos	-
2SC4204	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,30V,0,7A,B>800	7c	Sanyo	(2SC3070,2SC3225,2SC3673,2SD1582)
2SC4205	Si-NPN	Sw,Pow,400/400V,5A,40W,<1/3,5µS	17j$	Rhm	MJE52T..53T,2SC2827,2SC3056..
2SC4206	Si-NPN	Sw-Reg,900/600V,6A,80W,<1/4µS	18j$	Fjd	BU903,BU426A,2SC3536,2SC3636..
2SC4207	Si-NPN	Dual,60V,0,15A,>80MHz	45ba1	Tos	-
2SC4207-BL	Si-NPN	-	45	Tos	→2SC4207
2SC4207-GR	Si-NPN	-	45	Tos	→2SC4207
2SC4207-Y	Si-NPN	-	45	Tos	→2SC4207
2SC4208	Si-NPN	GenP,30V,0,5A,1W,150MHz	7c(9mm)	Mat	BC635,2SC2236,2SD1146,2SD1331..
2SC4208A	Si-NPN	=2SC4208:60V	7c(9mm)	-	BC637,2SC3328,2SD1207,2SD1835
2SC4209	Si-NPN	GenP,80V,0,3A,100MHz	35a	Toshiba	BCW66,2SD1782
2SC4209-O	Si-NPN	-	35	Tos	→2SC4209
2SC4209-Y	Si-NPN	-	35	Tos	→2SC4209
2SC421..422	Si-NPN	-		Oki	-
2SC4210	Si-NPN	GenP,35V,0,8A,120MHz	35a	Toshiba	BCW65..66,2SC3265,2SD1782
2SC4210-O	Si-NPN	-	35	Tos	→2SC4210
2SC4210-Y	Si-NPN	-	35	Tos	→2SC4210
2SC4211	Si-NPN	GenP,55V,0,15A,200MHz	35a(2mm)	Sanyo	BC848W,2SC4116,2SC4141,2SC4177..
2SC4212	Si-NPN	=2SC3946:SW	14h$	Mat	BF850,2SC3418
2SC4213	Si-NPN	Hi-Ueb,50V,0,3A,B=150(reveµse)	35a(2mm)	Tos	-
2SC4213A	Si-NPN	-	35(2mm)	Tos	→2SC4213A
2SC4213B	Si-NPN	-	35(2mm)	Tos	→2SC4213B
2SC4214	Si-NPN	TV-UHF-Tuner,25V,0,02A,850MHz	44zf	Tos	-
2SC4215	Si-NPN	VHF,40V,0,02A,550MHz	35a(2mm)	Tos	BF599,BF799,BFS20,2SC3931..32
2SC4215-O	Si-NPN	-	35(2mm)	Sanyo	→2SC4215
2SC4215-R	Si-NPN	-	35(2mm)	Tos	→2SC4215
2SC4215-Y	Si-NPN	-	35(2mm)	Tos	→2SC4215
2SC4216	Si-NPN-Digital	=2SC3901:	40f	Sanyo	→2SC3901
2SC4217	Si-NPN	Sw,Vid-Out,Hi-def,300V,0,2A,70MHz	14b	Sanyo	2SC3789..90,(2SC3417,2SC3503)
2SC4218	Si-NPN	Vid,300/300V,0,1A,0,5W,70MHz	7c	Sanyo	BF299,BF420A,2SC3249,2SC3468..
2SC4219	Si-NPN	Sw,Pow,500/400V,4A,40W,<0,5/2,8µS	30j$	Sanyo	2SC4597
2SC4220	Si-NPN	Sw,Pow,500/400V,7A,50W,<0,5/2,8µS	30j$	Sanyo	2SC4598
2SC4221	Si-NPN	Sw,Pow,800/500V,3A,40W,<0,5/3,3µS	30j$	Sanyo	2SC4171,2SC4599
2SC4222	Si-NPN	Sw,Pow,800/500V,5A,50W,<0,5/3,3µS	30j$	Sanyo	2SC4172,2SC4600
2SC4223	Si-NPN	Sw,Pow,1100/800V,1,5A,40W,<0,5/3,3µS	30j$	Sanyo	2SC4601
2SC4224	Si-NPN	Sw,Pow,1100/800V,3A,50W,<0,5/3,3µS	30j$	Sanyo	2SC4602
2SC4225	Si-NPN	VHF/UHF,25V,0,07A,4000MHz	35a(2mm)	Nec	2SC3937
2SC4225	Si-NPN	VHF/UHF,25V,0,07A,4000MHz,B=100-200	35a(2mm)	Nec	-
2SC4225	Si-NPN	VHF/UHF,25V,0,07A,4000MHz,B=40-120	35a(2mm)	Nec	-
2SC4225-R2	Si-NPN	-	35(2mm)	Nec	→2SC4225
2SC4225-R3	Si-NPN	-	35	Nec	→2SC4225
2SC4226	Si-NPN	VHF/UHF,20V,0,1A,4500MHz	35a(2mm)	Nec	-
2SC4226	Si-NPN	VHF/UHF,20V,0,1A,4500MHz,B=125-250	35a(2mm)	Nec	-
2SC4226	Si-NPN	VHF/UHF,20V,0,1A,4500MHz,B=40-80	35a(2mm)	Nec	-
2SC4226	Si-NPN	VHF/UHF,20V,0,1A,4500MHz,B=70-140	35a(2mm)	Nec	-

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2SC4226-R22	Si-NPN	-	35(2mm)	Nec	→2SC4226
2SC4226-R23	Si-NPN	-	35(2mm)	Nec	→2SC4226
2SC4226-R24	Si-NPN	-	35(2mm)	Nec	→2SC4226
2SC4226-R25	Si-NPN	-	35(2mm)	Nec	→2SC4226
2SC4227	Si-NPN	VHF/UHF,20V,65mA,7000MHz	35a	Nec	BFS520,2SC5085
2SC4227	Si-NPN	VHF/UHF,20V,65mA,7GHz B=70-150	35a	Nec	-
2SC4227	Si-NPN	VHF/UHF,20V,65mA,7GHz,B=110-240	35a	Nec	-
2SC4227	Si-NPN	VHF/UHF,20V,65mA,7GHz,B=40-90	35a	Nec	-
2SC4227-R32	Si-NPN	-	35(2mm)	Nec	→2SC4227
2SC4227-R33	Si-NPN	-	35(2mm)	Nec	→2SC4227
2SC4227-R34	Si-NPN	-	35(2mm)	Nec	→2SC4227
2SC4227-R35	Si-NPN	-	35(2mm)	Nec	→2SC4227
2SC4228	Si-NPN	VHF/UHF,20V,35mA,8000MHz	35a	Nec	BFR182W,2SC5065,2SC5090,2SC5190
2SC4228	Si-NPN	VHF/UHF,20V,35mA,8000MHz,B=125-250	35a	Nec	-
2SC4228	Si-NPN	VHF/UHF,20V,35mA,8000MHz,B=50-100	35a	Nec	-
2SC4228	Si-NPN	VHF/UHF,20V,35mA,8000MHz,B=80-160	35a	Nec	-
2SC4228-R42	Si-NPN	-	35(2mm)	Nec	→2SC4228
2SC4228-R43	Si-NPN	-	35(2mm)	Nec	→2SC4228
2SC4228-R44	Si-NPN	-	35(2mm)	Nec	→2SC4228
2SC4228-R45	Si-NPN	-	35(2mm)	Nec	→2SC4228
2SC4229	Si-NPN	UHF,30V,0,02A,1000MHz	35a	Hit	BFS17,BFS17,2SC3161,2SC3099..
2SC423	Si-NPN	HF-Ant/Dr,40V,0,3A,0,5W,500MHz	2a$	Sanyo	BFR36,BFW16..17,BFX55
2SC4230	Si-NPN	Sw,Pow,1200/800V,2A,50W,<0,5/3,8µS	17j$	Shi	BU1706AB,BU505,MJE8500,2SC3178
2SC4231	Si-NPN	=2SC4230:30W	15c	Shi	BU505F,2SC4234,(MJE8500,2SC3178)
2SC4232	Si-NPN	=2SC4230:70W	16j$	Shi	BU705,2SC3483,2SD1493..94,2SD1543
2SC4233	Si-NPN	Sw,Pow,1200/800V,3A,60W,<0,5/3,8µS	17j$	Shi	BU505,MJE8502,2SC3050
2SC4234	Si-NPN	=2SC4233:45W	15c	Shi	BU505F,(MJE8502,2SC3050)
2SC4235	Si-NPN	=2SC4233:80W	16j$	Shi	BU706,2SC3387,2SC3642
2SC4236	Si-NPN	Sw,Pow,1200/800V,6A,100W,<0,4/3,8µS	16j$	Shi	BUV89,2SC3466,2SC3643
2SC4237	Si-NPN	Sw,Pow,1200/800V,10A,150W,<0,5/3,8µS	16j$	Shi	BUV48B,C,2SC3644,2SC4023
2SC4238	Si-NPN	VHF,30V,0,05A,1300MHz	35a	Mat	BFR53,2SC3014,2SC3016,2SC4082
2SC4239	Si-NPN	UHF/AF,15V,0,05A,2000MHz	35a(2mm)	Mat	2SC4780,2SC5110
2SC424	Si-NPN	=2SC423:0,2W	2a	Sanyo	BFR36,BFW16..17,BFX55
2SC4240	Si-NPN	HF-Pow,20V,3A,20W	-	Mit	-
2SC4241	Si-NPN	UHF,20V,0,08A,6500MHz	44zf	Nec	2SC4093
2SC4242	Si-NPN	Sw,Pow,450/400V,7A,40W,1/3µS	17j$	Fjd	MJE13006,2SC3170,2SC4055,2SC4106..
2SC4243	Si-NPN	Vid,300/300V,0,1A,1W,100MHz	78b	Rhm	2SC2924,2SC3408,2SC3805,2SC4019,..
2SC4244	Si-NPN	UHF-Pre,25V,0,02A,850MHz	35a(2mm)	Toshiba	BFS17W,BFS17W,2SC3933,2SC4780..
2SC4245	Si-NPN	UHF-Mix,30V,0,05A,2400MHz	35a(2mm)	Tos	2SC4780,2SC5110
2SC4246	Si-NPN	UHF-Osc,30V,0,05A,1500MHz	35a(2mm)	Tos	2SC4780,2SC5110
2SC4247	Si-NPN	UHF-Osc,20V,0,03A,4000MHz	35a(2mm)	Tos	BFR93W,2SC4903,2SC5107
2SC4248	Si-NPN	UHF-Osc,20V,0,03A,4000MHz	35a(2mm)	Tos	BFR93W,2SC4903,2SC5107
2SC4249	Si-NPN	VHF-V,30V,0,02A,650MHz	35a(2mm)	Tos	BFS17W,BFS17W,2SC3933,2SC4780..
2SC425	Si-NPN	=2SC423:20V	2a$	Sanyo	BFR36,BFW16..17,BFX55
2SC4250	Si-NPN	VHF-Mix,30V,0,05A,1400MHz	35a(2mm)	Tos	BFS17W,BFS17W,2SC3933,2SC4780..
2SC4251	Si-NPN	VHF-Osc,30V,0,05A,1100MHz	35a(2mm)	Tos	BFS17W,BFS17W,2SC3933,2SC4780..
2SC4252	Si-NPN	VHF-Osc,20V,0,03A,2000MHz	35a(2mm)	Tos	BFR93W,2SC4903,2SC5107
2SC4253	Si-NPN	TV-IF-Out,30V,0,05A,600MHz	35a(2mm)	Tos	BFS17W,BFS17W,2SC3933,2SC4780..
2SC4254	Si-NPN	GenP,50V,0,1A,230MHz	35a(2mm)	Hitachi	BC846W,2SC4081,2SC4128,2SC4177..
2SC4255	Si-NPN	TV-VHF,20V,0,03A,2000MHz	35a	Tos	BFS17,BFR53,2SC3099,2SC3773..
2SC4256	Si-NPN	Dynamic Focus,1500/1200V,0,01A,5W	17j$	Sanyo	2SC4257,2SC4451
2SC4257	Si-NPN	Dynamic Focuss,1500/1200V,0,03A,7W	17j$	Sanyo	2SC3675
2SC4258	Si-NPN	=2SC710:	35a(2mm)	Mit	2SC3931,2SC3936,2SC5020
2SC4258-B	Si-NPN	-	35(2mm)	Mit	→2SC4258
2SC4258-C	Si-NPN	-	35(2mm)	Mit	→2SC4258
2SC4258-D	Si-NPN	-	35(2mm)	Mit	→2SC4258
2SC4259	Si-NPN	-	35(2mm)	Hit	→2SC4259
2SC426	Si-NPN	=2SC423:20V,0,2W	2a	Sanyo	BFR36,BFW16..17,BFX55
2SC4260	Si-NPN	-	35(2mm)	Hit	→2SC4260
2SC4261	Si-NPN	-	35(2mm)	Hit	→2SC4261
2SC4262	Si-NPN	-	35(2mm)	Hit	→2SC4262
2SC4263	Si-NPN	-	35(2mm)	Hit	→2SC4263
2SC4264	Si-NPN	-	35(2mm)	Hit	→2SC4264
2SC4265	Si-NPN	-	35(2mm)	Mit	→2SC4265

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2SC4266	Si-NPN	=2SC3928:0,3W	41c	Mit	BC167,BC182,BC237,BC547,2SD767..
2SC4267	Si-NPN	AM/FM,-/20V,15mA,>450MHz	35a	Mat	BF554,BFS18..19,2SC2404,2SC2778..
2SC4269	Si-NPN	UHF,30V,0,05A,1200MHz	35a	Sanyo	BFS17,BFS17,2SC3016,2SC3161..
2SC427	Si-NPN	GenP,40V,0,1A,0,3W,350MHz	2a$	Sanyo	BC167,BC182,BC237,BC547,2N3904..
2SC4270	Si-NPN	UHF,25V,0,05A,3000MHz	35a	Sanyo	BFT75,2SC3014,2SC3161,2SC3772..73
2SC4271	Si-NPN	Vid-Out,Hi-def,30V,0,3A,5W,2200MHz	14h$	Sanyo	2SC3595
2SC4272	Si-NPN	27MHz-CB,75V,1A,Pq=1,8W(27MHz)	39b	Sanyo	(BCX56,2SD1005,2SD1368,2SD1422,..)
2SC4273	Si-NPN	Sw,Pow,500/400V,5A,40W,<1/3µS	17j$	Fjd	BUT93,2SC2535,2SC2827,2SC3830..
2SC4274	Si-NPN	Sw,Pow,500/400V,10A,40W,<1/3µS	17j$	Fjd	MJE13008,2SC3562,2SC4107,2SC4164..
2SC4275	Si-NPN	Sw,Pow,500/400V,10A,80W,<1/3µS	18j$	Fjd	BUP23,2SC2828,2SC3042,2SC4138..
2SC4276	Si-NPN	Sw,Pow,500/400V,15A,80W,<1/3µS	18j$	Fjd	BUP23,2SC3435,2SC3520,2SC4139..
2SC4277	Si-NPN	Sw,Pow,500/400V,5A,80W,<1/3µS	16c(j$)	Rhm	TIP58A,2SC2962,2SC3083
2SC4278	Si-NPN	Sw,Pow,150/150V,10A,100W,20MHz	16c(j$)	Rhm	BD245D,2SC2837,2SC2987A,2SD1703..
2SC428	Si-NPN	=2SC427:20V	2a$	Sanyo	BC168,BC183,BC238,BC548,2N3904..
2SC4283	Si-NPN	Sw,Pow,1200/800V,3A,50W,<0,5/3,8µS	18c	Sak	2SC4583
2SC4284	Si-NPN	Sw,Pow,1400/600V,8A,150W,<1/4,3µS	23a$	Tos	MJ8505,2SC3594
2SC4285	Si-NPN	Sw,Pow,1400/600V,10A,150W,<1/4,3µS	23a$	Tos	BUX88,MJ8505
2SC4286	Si-NPN	=2SC4284:100W	77c(j$)	Tos	-
2SC4287	Si-NPN	=2SC4285:100W	77c(j$)	Tos	-
2SC4288	Si-NPN	Sw,Pow,HD,Hi-res,1400/600V,12A,200W	77j$	Tos	2SC3995,2SC4096,2SC4111
2SC4288A	Si-NPN	=2SC4288:1500/600V	77j$	-	2SC3995,2SC4111,BU4540AL
2SC4289	Si-NPN	Sw,Pow,HD,Hi-res,1400/600V,16A,200W	77j$	Tos	2SC3996
2SC4289A	Si-NPN	=2SC4288:1500/600V	77j$	-	2SC3996,BU4540AL
2SC429	Si-NPN	Min,FM,25V,0,01A,380MHz	24b	Nec	(BF198..199,BF224..225,BF314,..)
2SC4290	Si-NPN	Sw,Pow,HD,Hi-res,1400/600V,20A,200W	77j$	Tos	2SC3997,2SC4897,2SD2356
2SC4290A	Si-NPN	=2SC4288:1500/600V	77j$	-	2SC3997,2SC4897,2SD2356,BU4550AL
2SC4291	Si-NPN+Diode	HD,Hi-def,1500/800V,5A,100W	18j$	Sanyo	2SC3481..82,2SC3681,BU4507DX,(BU2508D)
2SC4292	Si-NPN+Diode	HD,Hi-def,1500/800V,6A,100W	18j$	Sanyo	2SC3482,2SC3681,(BU2508D)
2SC4293	Si-NPN+Diode	=2SC4291:Iso,50W	18c	Sanyo	2SC3892A,2SC4122,BU4507DX,(BU2508DF)
2SC4294	Si-NPN+Diode	=2SC4292:Iso,50W	18c	Sanyo	2SC3892A,2SC4122,BU4508DX,(BU2508DF)
2SC4295(M)	Si-NPN	Sw,400/400V,0,1A,1W,1/7,2µS	9c	Rhm	BF487,MPSA45,2SC3469,2SD1385..
2SC4296	Si-NPN	Sw-Reg,500/400V,10A,75W,<1/3,5µS	18c	Sak	2SC4423,2SC4459,(2SC4138)
2SC4297	Si-NPN	Sw-Reg,500/400V,12A,75W,<1/3,5µS	18c	Sak	BUP23BF,2SC4423,2SC4459,(2SC4139)
2SC4298	Si-NPN	Sw-Reg,500/400V,15A,80W,<1/3,5µS	18c	Sak	BUP23BF,2SC4424,(2SC4139)
2SC4299	Si-NPN	Sw-Reg,900/800V,3A,70W,<1/6µS	18c	Sak	BUW11AF,2SC4426,2SC4445
2SC42A	Si-NPN	=2SC41:200V	23a$	-	BD245F,2SC2262,2SD555,2SD751..
2SC43	Si-NPN	=2SC41:100V,B>4	23a$	Son	BD245C,BDV95,BDX95,2N5758..
2SC430	Si-NPN	=2SC429:420MHz	24b	Nec	(BF198..199,BF224..225,BF314,..)
2SC4300	Si-NPN	Sw-Reg,900/800V,5A,75W,<1/6µS	18c	Sak	BUW11AF,2SC4428,2SC4586
2SC4301	Si-NPN	Sw-Reg,900/800V,7A,80W,<1/6µS	18c	Sak	BUW12AF,BUV47AFI,2SC4429
2SC4302	Si-NPN	Sw-Reg,900/800V,5A,75W,<1/4,5µS	18c	Sak	BUW11AF,2SC4300,2SC4428
2SC4303	Si-NPN	Sw,Pow,1400/800V,6A,80W,<1/4,3µS	18c	Sak	BU508AF,2SC4941,2SD1546,2SD1656,..
2SC4303A	Si-NPN	=2SC4303:1500/800V	18c	-	BU508AF,2SC4941,2SD1546,2SD1656,..
2SC4304	Si-NPN	Sw-Reg,900/800V,3A,35W,<0,7/4,7µS	17c	Sak	BUT11AF,2SC3559,2SC4517,2SC4908..
2SC4305	Si-NPN	Sw,Pow,100/40V,7A,40W,<1/3,5µS	15j$	Nec	BD543C,BD711,BD801,MJE15028..
2SC4306	Si-NPN	Sw,Pow,Lo-sat,30V,8A,15W,<300/1150nS	30j$	Sanyo	2SC4668,2SD1804
2SC4308	Si-NPN	VHF-A,30V,0,3A,0,6W,2500MHz	7f	Hit	2SC4693
2SC4309	Si-NPN	Sw,Pow,1000/800V,6A,150W,<500/2130nS	77j$	Mat	2SC3738,2SC3982A,2SC3992
2SC431	Si-NPN	Sw,Pow,150/100V,30A,200W,B>10	68a$	Shi	2SC1299,2SC1301,2SC1872,2SC2128,BUX22…
2SC4310	Si-NPN	Sw,Pow,900/800V,6A,50W,<500/3500nS	17j$	Shi	BUT11(A),BUT18(A),BUT56(A)..
2SC4311	Si-NPN	=2SC4310:Iso,40W	15c	Shi	BUT11(A)F,BUT18(A)F,BUV46(A)FI..
2SC4312	Si-NPN	Sw,Pow,900/800V,6A,80W,<500/3500nS	16j$	Shi	BUW11A,BUW131A,2SC3535..36..
2SC4313	Si-NPN	Sw,Pow,900/800V,10A,100W,<500/3500nS	16j$	Shi	BUV47A,BUW12A,2SC3637..38
2SC4314	Si-NPN	Sw,Pow,900/800V,15A,130W,<500/3500nS	16j$	Shi	BUV48A,BUW13A,BUW133A,2SC3638
2SC4315	Si-NPN	VHF/UHF,LN,20V,0,08A,7GHz	44ze	Tos	-
2SC4316	Si-NPN	VHF/UHF,LN,20V,40mA,9000MHz	7f	Tos	-
2SC4317	Si-NPN	-	35	Tos	→2SC4317
2SC4318	Si-NPN	-	39	Tos	→2SC4318
2SC4319	Si-NPN	-	25	Tos	→2SC4319
2SC432	Si-NPN	=2SC431:B>20	68a$	Shi	2SC1299,2SC1301,2SC1872,2SC2128,BUX22…
2SC4320	Si-NPN	-	44	Tos	→2SC4320
2SC4321	Si-NPN	-	35(2mm)	Tos	→2SC4321
2SC4322	Si-NPN	VHF/UHF,LN,10V,25mA,10GHz	35a	Toshiba	BFR505,2SC5094
2SC4323	Si-NPN	-	25	Tos	→2SC4323

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2SC4324	Si-NPN	-	44	Tos	→2SC4324
2SC4325	Si-NPN	-	35(2mm)	Tos	→2SC4325
2SC4326(LK)	Si-NPN	UHF,12V,0,05A,800MHz	35a	Rhm	BFS17,BFS17,2SC3016,2SC3161..
2SC4326LK-Q	Si-NPN	-	35	Rhm	→2SC4326LK
2SC4326LK-R	Si-NPN	-	35	Rhm	→2SC4326LK
2SC4326LK-S	Si-NPN	-	35	Rhm	→2SC4326LK
2SC4327	Si-NPN	Motor-Dr,Lo-sat,50V,7A,25W,115MHz	17c	Sak	2SC3747..48,2SC4550,2SD1444A
2SC4328	Si-NPN	Sw,Pow,lo-sat,150V,5A,30W,<300/1900nS	17j$	Nec	-
2SC4329	Si-NPN	Sw,Pow,lo-sat,150V,7A,35W,<300/1900nS	17j$	Nec	-
2SC433	Si-NPN	=2SC431:200/140V	68a$	Shi	2SC1299,2SC1301,2SC1873,2SC2128,BUX22...
2SC4330	Si-NPN	Sw,Pow,150V,10A,40W,<300/1900nS	17j$	Nec	-
2SC4331(Z)	Si-NPN	Lo-sat,150/100V,5A,15W,150MHz	30j$	Nec	2SC4343
2SC4332(Z)	Si-NPN	Sw,Pow,100V,5A,15W,<300/1800nS	30j$	Nec	2SC3303,2SC4344
2SC4333(Z)	Si-NPN	Sw,Pow,40V,7A,15W,<300/1800nS	30j$	Nec	2SD1804
2SC4334	Si-NPN	=2SC4328:Iso,25W	17c	Nec	2SC3566,2SC3696
2SC4335	Si-NPN	=2SC4329:Iso,30W	17c	Nec	2SC3568,2SC3697,2SD1792
2SC4336	Si-NPN	=2SC4330:Iso,30W	17c	Nec	2SC3568,2SC3698,2SD1794
2SC4337(Z)	Si-N-Darl+Di	Sw,Pow,60V,±1A7W,B=10000	30j$	Nec	2SC2871,2SD1598,2SD1800
2SC4338(Z)	Si-N-Darl+Di	Sw,Pow,80V,±2A,8W,B=10000	30j$	Nec	2SD1817,2SD1980
2SC4339(Z)	Si-N-Darl+Di	Sw,Pow,150/100V,±3A,9W,B=10000	30j$	Nec	-
2SC434(A)	Si-NPN	=2SC431:200/140(A=200/200)V,B>20	68a$	Shi	2SC1299,2SC1301,2SC1873,2SC2128..
2SC4340	Si-N-Darl+Di	=2SC4337:8W	14h$	Nec	BD875,BD877,BD879,BDX42..44
2SC4341	Si-N-Darl+Di	=2SC4338:10W	14h$	Nec	(BD679,BD681,BD683,BD779,2N6039)
2SC4342	Si-N-Darl+Di	=2SC4339:12W	14h$	Nec	-
2SC4343(Z)	Si-NPN	Sw,Pow,150V,7A,18W,<300/1900nS	30j$	Nec	-
2SC4344(Z)	Si-NPN	Sw,Pow,100V,7A,18W,<300/1800nS	30j$	Nec	-
2SC4345(Z)	Si-NPN-Darl	Sw,Pow,100V,5A,12W,B=10000	30j$	Nec	-
2SC4346(Z)	Si-NPN	Sw,Pow,500/400V,5A,18W,<700/2800nS	30j$	Nec	..(BUT11(A),BUV46(A),2SC3497,..)
2SC4347	Si-N-Darl+Di	60V,5A,25W,B=10000	15j$	Nec	-
2SC4348	Si-N-Darl+Di	Sw,Pow,100V,±5A,25W,B=10000	15j$	Nec	-
2SC4349	Si-N-Darl+Di	Sw,Pow,100V,8A,30W,B=10000	15j$	Nec	-
2SC435	Si-NPN	=2SC431:300/200V	68a$	Shi	2SC1299,2SC1302,2SC1401,2SC1873..
2SC4350	Si-N-Darl+Di	Sw,Pow,100V,10A,40W,B=10000	15j$	Nec	-
2SC4351	Si-N-Darl+Di	=2SC4347:Iso,20W	17c	Nec	-
2SC4352	Si-N-Darl+Di	=2SC4348:Iso,20W	17c	Nec	-
2SC4353	Si-N-Darl+Di	=2SC4350:Iso,25W	17c	Nec	-
2SC4354	Si-NPN	Sw,Pow,400/400V,2A,15W,<1/3,5µS	78c	Rhm	(BUX84..85,2SC2738,2SC3169,..)
2SC4355	Si-NPN	Sw,Pow,100V,4A,10MHz	78c	Rhm	-
2SC4356	Si-NPN	GenP,60V,2A,0,9W,80MHz	7c(9mm)	Mit	2SC3328,2SD1014,2SD1207,2SD1146..
2SC4357	Si-NPN	=2SC4356:SMD	39b	Mit	2SC3647,2SC4132,2SD1623,2SD1422..
2SC4357-C	Si-NPN	-	39	Mit	→2SC4357
2SC4357-D	Si-NPN	-	39	Mit	→2SC4357
2SC4357-E	Si-NPN	-	39	Mit	→2SC4357
2SC4358	Si-NPN	35V,0,3A,2500MHz	17c	Mat	-
2SC4359	Si-NPN	Sw,Pow,900/800V,3A,70W,<700/2800nS	16c	Mat	BUW11AF,2SC4299,2SC4445
2SC436	Si-NPN	=2SC431:300/200V,B>20	68a$	Shi	2SC1299,2SC1302,2SC1401,2SC1873..
2SC4360	Si-NPN	-	35	Sanyo	→2SC4360
2SC4361	Si-NPN-Digital	Sw,50V,0,1A,0,3W,R1=4,7kΩR2=10kΩ	40c	Sanyo	AA1L3N,DTC143XS,KSR1005,UN421F
2SC4362	Si-NPN	-	35	Sanyo	→2SC4362
2SC4363	SI-NPN-Digital	Sw,50V,0,1A,0,3W,R1=R2=4,7kΩ	40c	Sanyo	AA1L3M,DTC143ES,RN1001,UN421L..
2SC4364	Si-NPN	UHF,25V,0,03A,3000MHz	35a	Sanyo	BF775,BFR35,2SC3014,2SC3098
2SC4365	Si-NPN	UHF,25V,0,05A,3000MHz	35a	Sanyo	BFT75,2SC3014,2SC3772..3773
2SC4366	Si-NPN	-	35	Hit	→2SC4366
2SC4367	Si-NPN	HF,30V,0,1A,0,6W,1000MHz	7c(9mm)	Hit	-
2SC4368	SI-NPN	AF,Sw-Pow,150/150V,1,5A,20W,4MHz	17c	Kec	2SC3298(A,B),2SC3567,2SC3695,2SC4159
2SC4369	Si-NPN	AF,Sw-Pow,30V,3A,15W,100MHz	17c	Kec	2SC3297,2SC3690,2SC1762,2SD1913
2SC437	Si-NPN	HF/Sw-Pow,100V,2A,13W,210MHz	2a$	Mit	(BD379,BD529,2SD1177..1178,..)
2SC4370	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,100MHz	17c	Kec	2SC3298(A,B),2SC3364,2SC4159,2SC4883A
2SC4371	Si-NPN	Sw,Pow,500/400V,5A,30W,<1/3,5µS	17c	Kec	2SC3570,2SC3573,2SC4073,2SC4418..
2SC4372	Si-NPN	GenP,200/150V,0,05A,120MHz	39b	Kec	BF620,BF622,2SC2880,2SC3380..
2SC4373	Si-NPN	GenP,120/120V,0,5A,120MHz	39b	Kec	2SC2881,2SD1007,2SD1418..19
2SC4374	Si-NPN	GenP,80V,0,4A,100MHz	39b	Kec	2SC2882,2SC3438,2SD875,2SD1667..
2SC4375	Si-NPN	GenP,30V,1,5A,120MHz	39b	Kec	2SC2982,2SC4377,2SD1621,2SD1766
2SC4376	Si-NPN	GenP,35V,0,8A,120MHz	39b	Kec	BCX54..56,2SC2884,2SC3444,2SC4539,..

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2SC4377	Si-NPN	GenP,30V,2A,150MHz	39b	Kec	2SD1119,2SD1620,2SD1766
2SC4378	Si-NPN	Vid-Pow,300/300V,0,2A,10W,70MHz	14b	Sanyo	(BF417,BF617,BF758..759,..)
2SC4379	Si-NPN	Sw,Pow,500/400V,15A,120W,<500/2100nS	16c(jS)	Mat	BUP23,2SC4139,2SC4434,2SC4424..
2SC438	Si-NPN	=2SC437:75V	2a$	Mit	(BD377,BD527,2SD1177..1178,..)
2SC4381	Si-NPN	TV-AF-Pow,150/150V,2A,25W,15MHz	17c	Sak	BDT31DF,2SC3298(A..B),2SC3567..
2SC4382	Si-NPN	=2SC4381:200/200V	17c	Sak	2SC3298B,2SD1587
2SC4383	Si-NPN	Sw,Pow,200/180V,8A,40W,<2/5µS	18c	Fjd	2SC4387,2SC5101,(BD245F,2SD751,..)
2SC4385	Si-NPN	AF,Sw-Pow,120/80V,6A,60W,20MHz	18c	Sak	2SC4689,2SC5099,2SD2064
2SC4386	Si-NPN	AF,Sw-Pow,160/120V,8A,75W,20MHz	18c	Sak	2SC5100,(BD245D..F,2SC2837,2SD1046)
2SC4387	Si-NPN	AF,Sw-Pow,200/140V,10A,80W,20MHz	18c	Sak	2SC4388,2SC5101,(2SC3263,2SC3855)
2SC4388	Si-NPN	AF,Sw-Pow,200/180V,15A,85W,20MHz	18c	Sak	(2SC3263,2SC3856)
2SC4389	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,30V,2A,B>800	7c(9mm)	Sanyo	(2SD1581,2SD1779)
2SC439	Si-NPN	HF,25V,0,1A,0,5W,420MHz	2a$	Mit	BFX55,2N3299..3300,2N3724,2SC1385,..
2SC4390	Si-NPN	Hi-Ueb,Hi-beta,lo-sat,20V,2A,B>800	39b	Sanyo	2SD1950
2SC4391	Si-NPN	AF,80V,1A,1W,120MHz	9c	Mat	BC639,MPS651,2SC3669,2SD619..
2SC4392	Si-NPN	UHF,20V,30mA,6500MHz	35a(2mm)	Tos	BFR182W,2SC5065,2SC5090,2SC5190
2SC4393	Si-NPN	VHF/UHF,17V,70mA,5000MHz	35a(2mm)	Tos	BFS520,2SC3937
2SC4394	Si-NPN	VHF/UHF,20V,80mA,7000MHz	35a(2mm)	Toshiba	BFS520,2SC5085
2SC4396	Si-NPN-Digital	Sw,50V,0,1A,250MHz,R1=R2=47kΩ	35a(2mm)	Sanyo	DTC144EU,RN1304,UN5213
2SC4397	Si-NPN-Digital	Sw,50V,0,1A,250MHz,R1=R2=22kΩ	35a(2mm)	Sanyo	DTC124EU,RN1303,UN5212
2SC4398	Si-NPN-Digital	Sw,50V,0,1A,250MHz,R1=R2=10kΩ	35a(2mm)	Sanyo	DTC114EU,RN1302,UN5211
2SC4399	Si-NPN	HF,20V,30mA,320MHz	35a(2mm)	Sanyo	2SC3931..32,2SC3935,2SC5020
2SC44	Si-NPN	=2SC41:50V,B>4	23a$	Son	BD245,BDV91,BDX91,2N4914..
2SC440	Si-NPN	HF,25V,0,1A,0,5W,420MHz	2a$	Mit	BFX55,2N3299..3300,2N3724,2SC1385,..
2SC4400	Si-NPN	FM/VHF,40V,50mA,750MHz	35a(2mm)	Sanyo	-
2SC4401	Si-NPN	UHF,25V,30mA,3000MHz	35a(2mm)	Sanyo	BFR93W,2SC4905,2SC5107
2SC4402	Si-NPN	UHF,25V,50mA,3000MHz	35a(2mm)	Sanyo	2SC4780,2SC5110
2SC4403	Si-NPN	UHF,25V,70mA,3000MHz	35a(2mm)	Sanyo	2SC3937,2SC5085
2SC4404	Si-NPN	UHF,20V,70mA,5000MHz	35a(2mm)	Sanyo	BFS520,2SC3937,2SC5085
2SC4405	Si-NPN	UHF,20V,100mA,5000MHz	35a(2mm)	Sanyo	BFS540
2SC4406	Si-NPN	UHF,30V,50mA,1200MHz	35a(2mm)	Sanyo	BFS17W,BFS17W,2SC3933,2SC4780..
2SC4407	Si-NPN	UHF,25V,50mA,3000MHz	35a(2mm)	Sanyo	2SC4780,2SC5110
2SC4408	Si-NPN	Sw,Lo-sat,80V,2A,0,9W,100/600nS	7c(9mm)	Tos	2SC3328,2SD2485
2SC4409	Si-NPN	-	39	Tos	→2SC4409
2SC441	Si-NPN	HF,25V,0,1A,0,5W,420MHz	2a$	Mit	BFX55,2N3299..3300,2N3724,2SC1385,..
2SC4410	Si-NPN	-	35(2mm)	Mat	→2SC4410
2SC4411	Si-NPN	Vid-Out,Hi-def,100V,0,5A,15W,1200MHz	17j$	Sanyo	2SC4202
2SC4412	Si-NPN	CTV-Vid,-/300V,0,05A,70MHz	35a	Sanyo	BF820,2SC4061
2SC4413	Si-NPN	Hi-Ueb,Hi-beta,60V,0,1A,B>800	35a(2mm)	Sanyo	-
2SC4414	Si-NPN	Lo-sat,100V,0,5A,0,3W,120MHz,50/740nS	40c	Sanyo	-
2SC4415	Si-NPN	-	44	Hit	→2SC4415
2SC4416	Si-NPN	-	35	Hit	→2SC4416
2SC4417	Si-NPN	-	35(2mm)	Mat	→2SC4417
2SC4418	Si-NPN	Sw-Reg,500/400V,5A,30W,20MHz	17c	Sak	2SC3573,2SC4054,2SC4073,2SC4371..
2SC4419	Si-NPN	Sw,Pow,900/800V,6A,100W,<1?/4,8µS	18j$	Fjd	BUW11A,BUW132A,2SC3536,2SC3636..
2SC442	Si-NPN	HF,50V,0,1A,0,5W,420MHz	2a$	Mit	BFX55,2N3299..3300,2N3724,2SC1385,..
2SC4420	Si-NPN	Sw,Pow,900/800V,3A,70W,<700/2800nS	16c	Mat	BUW11AF,2SC4299,2SC4300,2SC4445..
2SC4421	Si-NPN	Sw,Pow,500/400V,3A,40W,<500/2100nS	17c	Mat	2SC3570,2SC4052,2SC4160,2SC4533..
2SC4422	Si-NPN	-	39	Hit	→2SC4422
2SC4423	Si-NPN	Sw,Pow,500/400V,12A,55W,20MHz	18c	Sanyo	2SC4297,(BUW13(A),BUV48(A..C,..)
2SC4424	Si-NPN	Sw,Pow,500/400V,16A,60W,20MHz	18c	Sanyo	2SC4298,(BUW13(A),BUV48(A..C,..)
2SC4425	Si-NPN	Sw,Pow,500/400V,25A,65W,20MHz	18c	Sanyo	2SC4461,(2SC3850,2SC4110)
2SC4426	Si-NPN	Sw,Pow,1100/800V,3A,45W,15MHz	18c	Sanyo	2SC4583,(2SC3387,2SC3460,2SC3642)
2SC4427	Si-NPN	Sw,Pow,1100/800V,4,5A,50W,15MHz	18c	Sanyo	2SC4882,(2SC3387,2SC3460,2SC3642)
2SC4428	Si-NPN	Sw,Pow,1100/800V,6A,55W,15MHz	18c	Sanyo	2SC4584,(BUV89,2SC3466,2SC3643)
2SC4429	Si-NPN	Sw,Pow,1100/800V,8A,60W,15MHz	18c	Sanyo	2SC4199,2SC4585,(BUV89,2SC3643,..)
2SC443	Si-NPN	FM-Driver,50V,0,5A,0,8W,200MHz	2a$	Mit	BFS23,BFX55,BLY34
2SC4430	Si-NPN	Sw,Pow,1100/800V,12A,65W,15MHz	18c	Sanyo	2SC4585,(BUV48B,C,2SC3552,2SC3644)
2SC4431	Si-NPN	AF/HF-Pow,120/120V,1,5A,20W,150MHz	17c	Nec	2SC3298(A,B),2SC3564,2SC4370,2SD1763+
2SC4432	Si-NPN	FM/VHF,40V,0,05A,750MHz	35a	Sanyo	BF599,BF799,BFS20,2SC3374..
2SC4433	Si-NPN	FM,40V,50mA,0,3W,750MHz	40c	Sanyo	BF314,BF502,BF505,BF507,BF562..
2SC4434	Si-NPN	Sw,Pow,500/400V,15A,120W,<500/2150nS	18j$	Sak	BUP23,2SC3435,2SC3520,2SC4139..
2SC4435	Si-NPN	HD,Hi-def,1500/800V,5A,100W	18j$	Sanyo	2SC3485..86,2SC3685,BU4508AX,(BU2508A,..)
2SC4436	Si-NPN	HD,Hi-def,1500/800V,6A,100W	18j$	Sanyo	2SC3486,2SC3685..86,BU4515AX,(BU2508A,..)

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2SC4437	Si-NPN	HD,Hi-def,1500/800V,5A,50W	18c	Sanyo	2SC3884A,2SC3894,BU4508AX,(BU2508AF)
2SC4438	Si-NPN	HD,Hi-def,1500/800V,6A,50W	18c	Sanyo	2SC3884A..85A,2SC3894,BU4515AX,(BU2508AF)
2SC4439	Si-NPN	Vid-Out,Hi-res,180V,0,3A,8W,400MHz	14b	Tos	S3936,2SC4564,2SC4623
2SC444	Si-NPN	FM-Driver,60V,0,5A,0,8W,220MHz	2a$	Mit	BFS23,BFX55,BLY34
2SC4440	Si-NPN	HD,Monochrome,600/400V,7A,30W	17c	Sanyo	BU307F
2SC4441	Si-NPN	HD,Monochrome,600/400V,10A,35W	17c	Sanyo	-
2SC4442	Si-NPN	Sw,Pow,500/400V,4A,45W,<500/2100nS	17c	Mat	2SC4054,2SC4073,2SC4160,2SC4371..
2SC4443	Si-NPN	Sw,20V,0,15A,700MHz	35a(2mm)	Sanyo	-
2SC4444	Si-NPN	VHF/IF,45V,0,05A,500MHz	35a	Mat	BFS17,BFS17,2SC3016,2SC3161
2SC4445	Si-NPN	Sw,Pow,900/800V,3A,60W,<700/4700nS	18c	Sak	BUW11AF,2SC4299,2SC4300,2SC4426
2SC4446	Si-NPN	Hi-Ueb,60V,0,15A,130MHz	35a(2mm)	Sanyo	-
2SC4448	Si-NPN	Vid-Out,Hi-res,250V,0,15A,10W,240MHz	17c	Tos	S3540
2SC4449	Si-NPN	Vid,300/300V,0,05A,0,6W,70MHz	7c	Sanyo	BF299,BF420(A),2SC3468
2SC445	Si-NPN	FM-Driver,80V,0,5A,0,8W,220MHz	2a$	Mit	(BFS23,BFX55,BLY34)
2SC4450	Si-NPN	Dynamic Focus,1500/1500V,5mA,6MHz	17j$	Sanyo	2SC4256
2SC4451	Si-NPN	Dynamic Focus,1500/1500V,15mA,6MHz	17j$	Sanyo	2SC4257
2SC4452	Si-NPN	-	35(2mm)	Sanyo	→2SC4452
2SC4453	Si-NPN	-	35	Sanyo	→2SC4453
2SC4454	Si-NPN	=2SC4455:0,3W	40c	Sanyo	→2SC4455
2SC4455	Si-NPN	Fast-Sw,40V,0,2A,0,6W,750MHz,<12/18nS	7e	Sanyo	BSS11,2N2368..69(A),2SC2901
2SC4457	Si-NPN	Sw-Reg,800/500V,4A,40W,<500/3300nS	18c	Sanyo	BUW11(A)F,2SC4300,2SC4586
2SC4458	Si-NPN	Sw-Reg,800/500V,7A,45W,<500/3300nS	18c	Sanyo	BUV47(A)FI,BUW12(A)F,2SC4301
2SC4459	Si-NPN	Sw-Reg,800/500V,10A,50W,<500/3300nS	18c	Sanyo	BUP23CF,BUV48(A)FI,BUW13(A)F
2SC446	Si-NPN	FM-Driver,60V,0,5A,0,8W,220MHz	2a$	Mit	BFS23,BFX55,BLY34
2SC4460	Si-NPN	Sw-Reg,800/500V,15A,55W,<500/3300nS	18c	Sanyo	BUP23CF,BUV48(A)FI,BUW13(A)F
2SC4461	Si-NPN	Sw-Reg,800/500V,25A,65W,<500/3300nS	18c	Sanyo	BUX98(A)PI
2SC4462	Si-NPN	-	35(2mm)	Hit	→2SC4422
2SC4463	Si-NPN	-	35(2mm)	Hit	→2SC4463
2SC4464	Si-NPN	UHF,15V,5mA,4000MHz	35a(2mm)	Hit	BFR92W,BFR181W,BFR280W
2SC4466	Si-NPN	AF-Pow,120/80V,6A,60W,20MHz	18j$	Sak	BD245C..F,2SC2681,2SC3181,2SD896..
2SC4467	Si-NPN	AF-Pow,160/120V,8A,80W,20MHz	18j$	Sak	BD245D..F,2SC2837,2SC2987A,2SD1047..
2SC4468	Si-NPN	AF-Pow,Lo-sat,200/140V,10A,80W,20MHz	18j$	Sak	(BD245F,2SC3855,2SC3263,2SC3856)
2SC447	Si-NPN	HF-Pow,75V,2A,25W,210MHz	49a	Mit	(BLY35,2N3632)
2SC4470	Si-NPN	UHF,20V,0,08A,7GHz	35d	Tos	-
2SC4471	Si-NPN	Sw,Pow,800/500V,4A,50W,<500/2100nS	17c	Mat	BUT11(A)F,BUT21CF,2SC3750,2SC3795
2SC4471A	Si-NPN	=2SC4471:900/500V	17c	-	BUT11AF,2SC3895A,2SC4518(A)
2SC4473	Si-NPN	Vid-Pow,120/120V,0,4A,10W,400MHz	17c	Sanyo	(2SC3781)
2SC4474	Si-NPN	Vid-Pow,200/200V,0,2A,10W,300MHz	17c	Sanyo	2SC3565,2SC4975,(2SC3782)
2SC4475	Si-NPN	TV,Dynamic Focus,2000/1800V,3mA	17j$	Sanyo	-
2SC4476	Si-NPN	TV,Dynamic Focus,2000/1800V,10mA	17j$	Sanyo	2SC4709
2SC4477	Si-NPN	TV-HD,330/150V,7A,30W,tf<300nS	17c	Sanyo	BU406F..407F,2SD1404,(2SC3590..91)
2SC4478	Si-NPN	=2SC4477:400/200V	17c	Sanyo	BU406F,(2SC3175,2SC3591)
2SC4479	Si-NPN	Vid-Out,Hi-res,100V,0,5A,10W,1100MHz	14b	Tos	2SC4563
2SC448	Si-NPN	HF-Pow,100V,2A,25W,190MHz	49a	Mit	-
2SC4480	Si-NPN	=2SC4389:	9c	Sanyo	→2SC4389
2SC4481	Si-NPN	Sw,15V,1,5A,0,9W,200MHz	9c	Sanyo	2SC2236,2SC4483,2SD1050,2SD1331..
2SC4482	Si-NPN	Sw,Lo-sat,60V,5A,1W,150MHz	9c	Sanyo	2SD1145
2SC4483	Si-NPN	AF,Lo-sat,30V,1,5A,1W,150MHz	9c	Sanyo	2SD1207,2SD1246..47,2SD2177
2SC4484	Si-NPN	AF,Sw,Lo-sat,30V,2,5A,1W,150MHz	9c	Sanyo	2SD879,2SD1207,2SD1347
2SC4485	Si-NPN	AF,Sw,Lo-sat,60V,1A,0,9W,150MHz	9c	Sanyo	2SD1207,2SD1616,2SD1835
2SC4486	Si-NPN	AF,Sw,Lo-sat,60V,2A,1W,150MHz	9c	Sanyo	2SC3328,2SD1207,2SD1835,2SD2069..
2SC4487	Si-NPN	AF,Sw,Lo-sat,60V,3A,1W,150MHz	9c	Sanyo	2SD1347
2SC4488	Si-NPN	AF,Sw,Lo-sat,120V,1A,1W,120MHz	9c	Sanyo	2SD1616A
2SC4489	Si-NPN	AF,Sw,Lo-sat,120V,2A,1W,120MHz	9c	Sanyo	-
2SC449	Si-NPN	HF-Pow,75V,2A,25W,190MHz	49a	Mit	(BLY35,2N3632)
2SC4490	Si-NPN	CRT,Hi-def,300/300V,0,1A,1W,70MHz	9c	Sanyo	2SC3468
2SC4491	Si-N-Darl+Di	+Z-Di(B→C),50V,1,2A,1W,B>1000	9c	Sanyo	-
2SC4492	Si-NPN	Sw,Pow,600/600V,0,02A,40MHz	30j$	Sanyo	(2SC4257,2SC4572)
2SC4493	Si-NPN	Sw,Pow,800/800V,0,02A,40MHz	30j$	Sanyo	(2SC4257,2SC4572)
2SC4494	Si-NPN	Lo-sat,60V,3A,25W,40MHz,Hi-B>500	17c	Sak	2SC3852,2SD2127,2SD2092,2SD1948
2SC4495	Si-NPN	=2SC4494:80V	17c	Sak	2SC3852,2SD1944,2SD2076
2SC4496	Si-N-Darl+Di	90V,8A,30W,400/3000nS,B>2000	17j$	Nec	2SD2024
2SC4497	Si-NPN	Mix,Video,300V,0,1A,70MHz	35a	Tos	BFN26,2SC4061
2SC4497-O	Si-NPN	-	35	Tos	→2SC4497

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2SC4497-R	Si-NPN	-	35	Tos	→2SC4497
2SC4498	Si-NPN-Digital	Sw,50V,0,1A,R1=2,2kΩ,R2=10kΩ	35a(2mm)	Sanyo	DTC123YU,UN521H
2SC4499L,S	Si-NPN	Sw,Pow,500/400V,0,5A,10W,<1/3µS	30j$	Hit	2SC3075,2SC3129,2SC3588
2SC45	Si-NPN	HF,45V,0,1A,0,5W,160MHz	2a$	Nec	BFW16..17,BFX55
2SC450	Si-NPN	HF-Pow,60V,2A,25W,210MHz	49a	Mit	(BLY35,2N3632)
2SC4500L,S	Si-NPN-Darl	Sw,Pow,60V,1A,8W,B>2000,100/600nS	30j$	Hit	2SC2871,2SD1598,2SD1800
2SC4501L,S	Si-NPN-Darl	Sw,Pow,30V,3A,10W,B>2000,400/1200nS	30j$	Hit	2SC3132,2SD1222,2SD1799
2SC4502	Si-NPN	TV-IF,50V,0,05A,1W,500MHz	9c	Mat	BF370,BF921,BF959
2SC4503	Si-NPN	Hi-Ueb,Lo-sat,100V,30A,80W,20MHz	18c	Sak	-
2SC4504	Si-NPN	Vid,Hi-res,30V,0,3A,3GHz	39b	Sanyo	-
2SC4505	Si-NPN	Sw,400/400V,0,1A,20MHz	39b	Rhm	2SC4548
2SC4505-N	Si-NPN	-	39	Rhm	→2SC4505
2SC4505-P	Si-NPN	-	39	Rhm	→2SC4505
2SC4505-Q	Si-NPN	-	39	Rhm	→2SC4505
2SC4506	Si-NPN	Vid,300/300V,0,1A,1,5W,100MHz	78c	Rhm	(BF417,BF459,2SC3503,2SC4147..)
2SC4507	Si-NPN	Sw,Pow,500/400V,5A,40W,<1/3µS	17c	Fjd	2SC4026,2SC4073,2SC4371,2SC4418..
2SC4508	Si-NPN	Sw,Pow,500/400V,10A,40W,<1/3µS	17c	Fjd	2SC3575,2SC3871,2SC4162,2SD1795..
2SC4509(R)	Si-NPN	Sw,Pow,500/400V,10A,80W,<1/3µS	18c	Fjd	BUW13(A)F,2SC4296..97,2SC4423..
2SC451	Si-NPN	HF-Pow,100V,1,2A,25W,180MHz	49a	Mit	-
2SC4510(R)	Si-NPN	Sw,Pow,500/400V,15A,80W,<1/3µS	18c	Fjd	BUV48(A)F,BUW13(A)F,2SC4298,2SC4424
2SC4511	Si-NPN	=2SC4512:Iso,30W	17c	Sak	BDT41BF..CF,2SC4335
2SC4512	Si-NPN	AF,Sw-Pow,120/80V,6A,50W,20MHz	17j$	Sak	BD243C..F,BD543D,2SC4329,2SD866
2SC4515	Si-NPN	UHF,15V,0,05A,0,2W,7GHz	44ze	Mat	-
2SC4516	Si-NPN	UHF,15V,0,08A,0,2W,8GHz	44ze	Mat	-
2SC4517	Si-NPN	Sw-Reg,900/550V,3A,30W,<700/4500nS	17c	Sak	BUT11AF,2SC4304,2SC3559,2SC3979A..
2SC4517A	Si-NPN	=2SC4517:1000/550	17c	-	BUT11AF,2SC3752,2SC3979A
2SC4518	Si-NPN	Sw-Reg,900/550V,5A,35W,<700/4500nS	17c	Sak	BUT11AF,BUT18AF,2SC3795A
2SC4518A	Si-NPN	=2SC4518:1000/550V	17c	-	BUT11AF,BUT18AF,2SC4898
2SC4519	Si-NPN	Sw,Lo-sat,60V,0,5A,<120/350nS	35a	Sanyo	-
2SC452	Si-NPN	HF-Pow,100V,1,2A,25W,180MHz	49a	Mit	-
2SC4520	Si-NPN	Sw,60V,1,5A,50/180nS	39b	Sanyo	-
2SC4521	Si-NPN	Sw,60V,3A,50/180nS	39b	Sanyo	-
2SC4522	Si-NPN	Sw,Pow,60V,5A,15W,50/180nS	30j$	Sanyo	2SC3074,2SC3518,2SC3592,2SD1803
2SC4523	Si-NPN	Sw,Pow,60V,8A,15W,50/180nS	30j$	Sanyo	2SC4668,2SD1804
2SC4524	Si-NPN	UHF-Pow,50V,2,5A,Pq>7W(1650MHz)	-	Mit	-
2SC4525	Si-NPN	UHF-Pow,50V,5A,Pq>20W(1650MHz)	-	Mit	-
2SC4526	Si-NPN	UHF-Pow,50V,7,5A,Pq>28W(1650MHz)	-	Mit	-
2SC4527	Si-NPN	TV-UHF-Tuner,30V,0,05A,1500MHz	35d	Tos	-
2SC4528	Si-N-Darl+Di	Int.Diode,1500/500V,10A,150W	77j$	Mat	-
2SC4529	Si-NPN	A,VHF-Pow,30V,0,3A,5W,>1500MHz	14h$	Hit	2SC4271
2SC453	Si-NPN	HF-Pow,90V,1,2A,25W,170MHz	49a	Mit	-
2SC4531	Si-NPN+Diode	TV-HD,1500/600V,10A,50W	18c	Tos	BU2520DF,BU4523DX,2SC4125,2SC4878,2SD1881
2SC4532	Si-NPN	TV-HD,Hi-res,1700/600V,10A,200W	77j$	Tos	BU4730AL,2SC4880
2SC4533	Si-NPN	Sw,Pow,500/400V,3A,30W,<1/3,3?	17c	Mat	2SC4052,2SC4160,2SC4421
2SC4537	Si-NPN	-	35(2mm)	Hit	→2SC4537
2SC4538(R)	Si-NPN	Sw,Pow,900/800V,5A,80W,<1?/4,8µS	18c	Fjd	BUW11(A)F,2SC4300,2SC4427,2SC4586,..
2SC4539	Si-NPN	Sw,Lo-sat,50V,1,2A,100/400nS	39b	Tos	2SC4409,2SD1623
2SC454(L)	Si-NPN	AM/FM-IF,30V,0,1A,230MHz,L=LN	9b,7c	Hit	BF240..241,BF254..255,BF594..595,..
2SC4540	Si-NPN	Sw,Lo-sat,80V,1A,100/500nS	39b	Tos	2SC4409
2SC4541	Si-NPN	Sw,Lo-sat,80V,3A,100/600nS	39b	Tos	-
2SC4542	Si-NPN	TV-HD,Hi-res,1500/600V,10A,50W	18c	Tos	BU2520AF,BU4525AX,2SC4759
2SC4543	Si-NPN	-	39	Mat	→2SC4543
2SC4544	Si-NPN	HD-Dr,Chroma-Out,300V,0,1A,8W,70MHz	17c	Tos	2SC3565,2SC3942,2SC3945,2SC4075
2SC4545	Si-NPN	AF-Pow,50V,1,5A,1,5W,150MHz	78b	Mat	2SD1682
2SC4546	Si-NPN	Sw-Reg,600/400V,7A,30W,<500/2150nS	17c	Sak	BU306F,BUT22BF..CF,2SC4056
2SC4547	Si-N-Darl+Di	85/85V,3A,30W,50MHz,B>2000	17j$	Sanyo	-
2SC4548	Si-NPN	-	39	Sanyo	→2SC4548
2SC4549	Si-NPN	=2SC3691	17c	Nec	→2SC3691
2SC455	Si-NPN	AM/FM-IF,230MHz	9b	Hitachi	BF240..241,BF254..255,BF594..595,..
2SC4550	Si-NPN	=2SC3692	17c	Nec	→2SC3692
2SC4551	Si-NPN	=2SC3693	17c	Nec	→2SC3693
2SC4552	Si-NPN	=2SC3694	17c	Nec	→2SC3694
2SC4553	Si-NPN+Diode	Hi-beta,Lo-sat,100V,7,5A,30W,100MHz	17c	Nec	-
2SC4554	Si-NPN+Diode	Hi-beta,Lo-sat,100V,15A,30W,100MHz	17c	-	-

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2SC4555	Si-NPN	Lo-sat,20V,0,5A,300MHz	35a(2mm)	Sanyo	2SD2483
2SC4557	Si-NPN	Sw-Reg,900/550V,10A,80W,<1/5,5µS	18c	Sak	BUP23CF,BUV48AFI,BUW13AF,2SC4587
2SC4558	Si-NPN	Hi-beta,Lo-sat,100V,6A,30W,B>700	17c	Sak	2SC4553,2SD2165
2SC4559	Si-NPN	Sw,Pow,500/400V,7A,40W,<1/3,3µS	17c	Mat	BU306F,2SC4056,2SC4130,2SC4161..
2SC456	Si-NPN	HF-A/Dr,50V,0,6A,0,75W,200MHz	2a$	Mat	BFS23,BLY34
2SC4560	Si-NPN	HD,Hi-res,1500/600V,10A,80W	77j$	Tos	BU2525A,2SC3688
2SC4561	Si-NPN	GenP,50V,0,05A,250MHz	35a	Matsushita	BC846..847,BCW71..72,BCW81..
2SC4561-Q	Si-NPN	-	35	Mat	→2SC4561
2SC4561-R	Si-NPN	-	35	Mat	→2SC4561
2SC4562	Si-NPN	-	35(2mm)	Mat	→2SC4562
2SC4562-Q	Si-NPN	-	35(2mm)	Mat	→2SC4562
2SC4562-R	Si-NPN	-	35(2mm)	Mat	→2SC4562
2SC4563	Si-NPN	Vid-Out,Hi-def,100V,0,5A,10W,1200MHz	14b	Sanyo	2SC4479
2SC4564	Si-NPN	Vid-Out,Hi-def,200V,0,3A,10W,400MHz	14b	Sanyo	2SC4623
2SC4565	Si-NPN	Vid-Out,Hi-def,140V,0,5A,10W,500MHz	14b	Sanyo	-
2SC4566	Si-NPN	=2SC4564:20W	17j$	Sanyo	-
2SC4567	Si-NPN	=2SC4565:20W	17j$	Sanyo	-
2SC4568	Si-NPN	UHF-Mix/Osc,20V,30mA,5,5GHz	35a	Nec	BFR93,2SC3011,2SC5106
2SC4568	Si-NPN	UHF-Mix/Osc,20V,30mA,5,5GHz,B=100-200	-	Nec	-
2SC4568	Si-NPN	UHF-Mix/Osc,20V,30mA,5,5GHz,B=40-80	-	Nec	-
2SC4568	Si-NPN	UHF-Mix/Osc,20V,30mA,5,5GHz,B=60-120	-	Nec	-
2SC4568-T72	Si-NPN	-	35	Nec	→2SC4568
2SC4568-T73	Si-NPN	-	35	Nec	→2SC4568
2SC4568-T74	Si-NPN	-	35	Nec	→2SC4568
2SC4569	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz	35a	Nec	BFR193,2SC3161,2SC3774..75
2SC4569	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz,B=100-200	-	Nec	-
2SC4569	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz,B=40-80	-	Nec	-
2SC4569	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz,B=60-120	-	Nec	-
2SC4569-T75	Si-NPN	-	35	Nec	→2SC4569
2SC4569-T76	Si-NPN	-	35	Nec	→2SC4569
2SC4569-T77	Si-NPN	-	35	Nec	→2SC4569
2SC457	Si-NPN	Dual,25V,0,05A,0,3W,200MHz	81bt	Nec	-
2SC4570	Si-NPN	UHF-Mix/Osc,20V,60mA,5.5GHz B=100-200	-	Nec	-
2SC4570	Si-NPN	UHF-Mix/Osc,20V,60mA,5.5GHz B=40-80	-	Nec	-
2SC4570	Si-NPN	UHF-Mix/Osc,20V,60mA,5.5GHz B=60-120	-	Nec	-
2SC4570-T72	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4570-T73	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4570-T74	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4570-T75	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4570-T76	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4570-T77	Si-NPN	-	35(2mm)	Nec	→2SC4570
2SC4571	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz B=40-80	-	Nec	-
2SC4571	Si-NPN	UHF-Mix/Osc,20V,60mA,5GHz B=60-120	-	Nec	-
2SC4572	Si-NPN	Sw,Pow,800/800V,20mA,40MHz	17j$	Sanyo	2SC4257,2SC4451
2SC4573	Si-N-Darl+Di	60V,4A,35W,B>2000,80MHz	17j$	Rhm	2SD2024,(BDW23A..C,BDW53A..D,..)
2SC4574	Si-N-Darl+Di	=2SC4573:Iso,30W	17c	Rhm	2SD1595,2SD1891
2SC4575	Si-N-Darl+Di	=2SC4573:Iso	78c	Rhm	-
2SC4576	Si-NPN	Sw,Pow,1400/700V,0,3A,20W,<2/4µS	17j$	Mat	2SC3676
2SC4577	Si-NPN	-	35	Sanyo	→2SC4577
2SC4578	Si-NPN	Sw,Pow,1700/900V,50mA,6MHz	17j$	Sanyo	-
2SC4579	Si-NPN	Sw,Pow,2000/900V,20mA,6MHz	17j$	Sanyo	2SC4913
2SC458(K,L,LG)	Si-NPN	GenP,30V,0,1A,0,2W,230MHz	9b,7c	Hit	BC169,BC184,BC239,BC549,2SC2675+
2SC4580	Si-NPN	Sw,Pow,600/450V,8A,50W,20MHz	18c	Shi	BUP22BF..CF,BUV47FI,AFI,BUW12F,AF
2SC4581	Si-NPN	Sw,Pow,600/450V,10A,65W,20MHz	18c	Shi	BUP23BF..CF,BUV48FI,AFI,BUW13F,AF
2SC4582	Si-NPN	Sw,Pow,600/450V,15A,75W,20MHz	18c	Shi	BUP23BF..CF,BUV48FI,AFI,BUW13F,AF
2SC4583	Si-NPN	Sw,Pow,1200/800V,3A,50W,<500/3800nS	18c	Shi	BU705F,2SD1543,2SD1653
2SC4584	Si-NPN	Sw,Pow,1200/800V,6A,65W,<500/3800nS	18c	Shi	BU508AF,2SC3885,2SC3895,2SC4144
2SC4585	Si-NPN	Sw,Pow,1200/800V,10A,85W,<500/3800nS	18c	Shi	BUH715,2SC3897,2SD1548
2SC4586	Si-NPN	Sw,Pow,900/800V,6A,65W,<500/3500nS	18c	Shi	BU426AF,BUV47AF,BUW12AF,2SC4428
2SC4587	Si-NPN	Sw,Pow,900/800V,10A,75W,<500/3500nS	18c	Shi	BUP23CF,BUV48AF,BUW13AF,2SC4430
2SC4589	Si-NPN	CTV/Display-HD,1500/800V,10A,50W	?18c	Hit	BU2520AF,2SC3897,2SC4199A,2SC4542
2SC459	Si-NPN	GenP,30V,0,1A,0,2W,230MHz	9b	Hitachi	BC168,BC183,BC238,BC548,2SD767..
2SC4591	Si-NPN	VHF/UHF,15V,50mA,9000MHz	35a	Hitachi	2SC3583,2SC3904,2SC4591,2SC5218
2SC4592	Si-NPN	-	44	Hit	→2SC4592

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2SC4593	Si-NPN	-	35(2mm)	Hit	→2SC4593
2SC4594	Si-NPN	Sw,70V,0,5A,0,9W,<45/70nS	7c(9mm)	Hit	(2N4014)
2SC4595	Si-NPN	Sw,Pow,Lo-sat,100/60V,12A,30W,120MHz	17c	Rhm	2SC4552
2SC4596	Si-NPN	Sw,Pow,Lo-sat,100/80V,5A,25W,120MHz	17c	Rhm	2SC3540,2SC3691,2SC4549
2SC4597	Si-NPN	Sw-Reg,500/400V,4A,40W,20MHz	30j$	Sanyo	2SC4219,(BUV46(A),BUT11(A),2SC3497)
2SC4598	Si-NPN	Sw-Reg,500/400V,7A,50W,20MHz	30j$	Sanyo	2SC4220,(BUT54,BUT56(A),2SC4055,+)
2SC4599	Si-NPN	Sw-Reg,800/500V,3A,40W,18MHz	30j$	Sanyo	2SC4171,2SC4221,(BUT11(A),BUV46(A))
2SC46	Si-NPN	HF/Sw,60V,0,3A,0,6W,180MHz	2a$	Fui	BFX55,BSW51..52,2N2218..19..
2SC460	Si-NPN	AM-Pre/Mix/Osc/IF,30V,0,1A,230MHz	9b,7c	Hit	BF240..241,BF254..255,BF594..595,..
2SC4600	Si-NPN	Sw-Reg,800/500V,5A,50W,18MHz	30j$	Sanyo	2SC4172,2SC4222,(BUT11(A),BUV46(A))
2SC4601	Si-NPN	Sw-Reg,1100/800V,1,5A,40W,15MHz	30j$	Sanyo	2SC4223,(2SC3178,2SC3456)
2SC4602	Si-NPN	Sw-Reg,1100/800V,3A,50W,15MHz	30j$	Sanyo	2SC4224,(2SC3050,2SC3457)
2SC4603(R)	Si-NPN	Sw,Pow,900/800V,3A,80W,<1?/4,8µS	18c	Fjd	BUW11(A)F,2SC4300,2SC4299,2SC4445,..
2SC4604	Si-NPN	AF,Sw,80V,3A,0,9W,100MHz	7c(9mm)	Tos	-
2SC4605	Si-NPN	=2SC4479:	17c	Tos	-
2SC4606	Si-NPN	=2SC1509:	9c	Mat	→2SC1509
2SC4607	Si-N-Darl+Di	Sw,Pow,1500V,10A,120W,300/2160nS,B>5	18j$	Mat	-
2SC4608	Si-NPN	HD,Hi-rés,1700/600V,8A,200W	77j$	Tos	S3934..35,2SC4532
2SC461	Si-NPN	FM-Preamp/Mix/Osc,30V,0,1A,230MHz	9b,7c	Hit	BF241,BF255,BF314,BFS02,BF505..
2SC4612	Si-NPN	Sw,180/160V,0,7A,1W,50/1060nS	9c	Sanyo	2SC3332,2SC4614
2SC4613	Si-NPN	Sw,180/160V,0,7A,1W,50/1060nS	14b	Sanyo	2SC3902,(2SC3116..17)
2SC4614	Si-NPN	Sw,180/160V,1,5A,1W,40/1280nS	9c	Sanyo	(2SD1812)
2SC4615	Si-NPN	Sw,Pow,400/400V,1A,15W,70MHz	30j$	Sanyo	2SC3362,2SC3632,2SD1053
2SC4616	Si-NPN	Sw,Pow,400/400V,2A,15W,60MHz	30j$	Sanyo	2SC3233,2SC3631
2SC4618(H)	Si-NPN	=2SC2413K	35a(1,6mm)	Rhm	2SC4915,2SC5021
2SC4619-M	Si-NPN	30V,50mA,150mW,110MHz,B=39..82	35(1,6mm)	Rhm	→2SC4619
2SC4619-N	Si-NPN	30V,50mA,150mW,110MHz,B=56..120	35(1,6mm)	Rhm	→2SC4619
2SC4619-P	Si-NPN	30V,50mA,150mW,110MHz,B=82..180	35(1,6mm)	Rhm	→2SC4619
2SC4619-Q	Si-NPN	30V,50mA,150mW,110MHz,B=120..270	35(1,6mm)	Rhm	→2SC4619
2SC462	Si-NPN	TV-IF,40V,0,05A,600MHz	5g	Hit	BF198..199,BF224..225,BF310..311,..
2SC4620	Si-NPN	=2SC4295(M):Pins=14mm	9c	Rhm	→2SC4295
2SC4621	Si-NPN	Sw,Pow,500/400V,7A,70W,30MHz	16c	Mat	BUP22BF..CF,BUV47FI,AFI,BUW12F,AF
2SC4622	Si-NPN	Sw,Pow,500/400V,7A,50W,<1/3µS	17j$	Fjd	MJE13006,2SC3170,2SC4106,2SC4055..
2SC4623	Si-NPN	Vid-Out,Hi-def,250V,0,3A,10W,400MHz	14b	Sanyo	-
2SC4624	Si-NPN	UHF-Out,35V,15A,Pq>45W(900MHz)	-	Mit	-
2SC4626	Si-NPN	-	35(1,6mm)	Mat	→2SC4626
2SC4626-A	Si-NPN	-	35(1,6mm)	Mat	→2SC4626
2SC4626-B	Si-NPN	-	35(1,6mm)	Mat	→2SC4626
2SC4626-C	Si-NPN	-	35(1,6mm)	Mat	→2SC4626
2SC4627	Si-NPN	-	35(1,6mm)	Mat	→2SC4627
2SC4627(J)	Si-NPN	=2SC2377:SMD	35a(1,6mm)	Mat	2SC4655,2SC4915,2SC5021
2SC4627-B	Si-NPN	-	35(1,6mm)	Mat	→2SC4627
2SC4627-C	Si-NPN	-	35(1,6mm)	Mat	→2SC4627
2SC4627-D	Si-NPN	-	35(1,6mm)	Mat	→2SC4627
2SC4627J	Si-NPN	-	35(1,6mm)	Mat	→2SC4627J
2SC4628	Si-NPN	UHF,20V,20mA,0,2W,>600MHz	7c	Hit	BF377..78,2SC2498,2SC2570(A),2SC3777
2SC4629	Si-NPN	UHF,15V,50mA,0,6W,8000MHz	7f	Hit	2SC3355,(2SC2590(A),2SC3512)
2SC463(H)	Si-NPN	VHF-AGC,40V,0,05A,600MHz	5g	Hit	BF225,BF310,BF314,BFS02,BF505..
2SC4630	Si-NPN	=2SC3675:Iso	17c	Sanyo	-
2SC4631	Si-NPN	=2SC3676:Iso	17c	Sanyo	-
2SC4632	Si-NPN	=2SC4256:Iso	17c	Sanyo	(2SC4450)
2SC4633	Si-NPN	=2SC4257:Iso	17c	Sanyo	(2SC4451)
2SC4634	Si-NPN	=2SC4450:Iso,10mA	17c	Sanyo	2SC4632
2SC4635	Si-NPN	=2SC4451:Iso,20mA	17c	Sanyo	2SC4633
2SC4636	Si-NPN	=2SC4475:Iso,10mA	17c	Sanyo	-
2SC4637	Si-NPN	=2SC4476:Iso,15mA	17c	Sanyo	-
2SC4638	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/4µS	17c	Mat	BUT11(A)F,2SC3353,2SC3795(A),2SC4518
2SC4639	Si-NPN	=2SC4640:SMD	35a	Sanyo	BC846,BCV71..72,2SC3323,2SC4076..
2SC464	Si-NPN	TV-IF,30V,0,02A,1100MHz	5g	Hit	BF198..199,BF224..225,BF310..311,..
2SC4640	Si-NPN	GenP,55V,0,15A,0,3W,200MHz	40c	Sanyo	BC174,BC182,BC546,2SC3245(A)..
2SC4641	Si-NPN	=2SC4640:0,5W	7c	Sanyo	BC174,BC182,BC546,2SC3245(A)..
2SC4642K	Si-NPN	GenP,50V,0,1A,180MHz	35a	Rohm	BC850,BCW71..72,2SC3323,2SC4076..
2SC4642K-R	Si-NPN	-	35	Rhm	→2SC4642K
2SC4642K-S	Si-NPN	-	35	Rhm	→2SC4642K

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2SC4643	Si-NPN	-	39	Hit	→2SC4643
2SC4644	Si-NPN	=2SC4002: 1W	9c	Sanyo	→2SC4002
2SC4645	Si-NPN	Sw, Dr, 400/400V, 1A, 1W, 70MHz	9c	Sanyo	-
2SC4646	Si-NPN	Sw, Dr, 400/400V, 2A, 1W, 60MHz	9c	Sanyo	-
2SC4647	Si-NPN	AF, Vid, 300/300V, 0, 1A, 0, 4W, >50MHz	7c	Hit	BF393, BF420A, 2SC3468, 2SC4218..
2SC4648	Si-NPN	=2SC4594: 0,5W	7c	Hit	2N4014
2SC4649	Si-NPN	=2SC2059K:	35a(1,6mm)	Rhm	-
2SC4649-M	Si-NPN	-	35(1,6mm)	Rhm	→2SC4649
2SC4649-N	Si-NPN	-	35(1,6mm)	Rhm	→2SC4649
2SC4649-P	Si-NPN	-	35(1,6mm)	Rhm	→2SC4649
2SC465	Si-NPN	VHF/UHF, 30V, 0,02A, 1100MHz	5g	Hit	BF377..378, BF689, BF763, 2N2857..
2SC4650	Si-NPN	CRT, Hi-def, 200/200V, 0, 1A, 1W, 150MHz	9c	Sanyo	2SC3467..68
2SC4652	Si-NPN	AF, Sw-Pow, -/120V, 8A, 80W	16c	Rhm	2SC4386, 2SC4690, 2SC5100
2SC4653	Si-NPN	AF, Sw-Pow, -/60V, 12A, 80W	16c	Rhm	2SC3762, 2SC4886
2SC4655	Si-NPN	-	35(1,6mm)	Mat	→2SC4655
2SC4655-B	Si-NPN	-	35(1,6mm)	Mat	→2SC4655
2SC4655-C	Si-NPN	-	35(1,6mm)	Mat	→2SC4655
2SC4656	Si-NPN	-	35(1,6mm)	Mat	→2SC4656
2SC4656-Q	Si-NPN	-	35(1,6mm)	Mat	→2SC4656
2SC4656-R	Si-NPN	-	35(1,6mm)	Mat	→2SC4656
2SC4657	Si-NPN	Sw, Pow, 60V, 5A, 15W, 120MHz, 100/1100nS	?30c	Tos	(2SC3518, 2SC3592, 2SD1803, 2SD1805)
2SC4658	Si-NPN	Sw, Pow, 100V, 5A, 15W, 120MHz, 200/1100nS	?30c	Tos	(2SC3303, 2SC4332)
2SC4659	Si-NPN	Sw, Pow, 500/400V, 5A, 15W, <1/3,5µS	?30c	Tos	(2SC4346)
2SC466(H)	Si-NPN	VHF/UHF, 30V, 0,02A, 1100(H=750)MHz	5g	Hit	BF377..378, BF689, BF763, 2N2857..
2SC4660	Si-NPN	Vid-Out, Hi-def, 30V, 0,3A, 8W, 2200MHz	14b	Sanyo	(2SC3595)
2SC4661	Si-NPN	UHF, 15V, 35mA, 5000MHz	35a(2mm)	Mat	BFR93W, 2SC4903, 2SC5107
2SC4661-Q	Si-NPN	-	35(2mm)	Mat	→2SC4661
2SC4661-R	Si-NPN	-	35(2mm)	Mat	→2SC4661
2SC4661-S	Si-NPN	-	35(2mm)	Mat	→2SC4661
2SC4662	Si-NPN	Sw, Pow, 500/400V, 5A, 30W, <1/3,5µS	17c	Sak	2SC3869, 2SC4026, 2SC4371, 2SC4418..
2SC4663	Si-NPN	Sw, Pow, 250/200V, 5A, 25W, <300/1100nS	?14c	Shi	2SC4073, 2SC4129, 2SC4371, 2SC4418..
2SC4664	Si-NPN	Sw, Pow, 250/200V, 8A, 30W, <300/1100nS	?14c	Shi	BU406F..407F, 2SC4161, 2SC4849..
2SC4666	Si-NPN	LN, Lo-sat, Hi-beta, 50V, 0, 15A, 250MHz	35a(2mm)	Tos	KTC4666
2SC4666A	Si-NPN	-	35(2mm)	Tos	→2SC4666A
2SC4666B	Si-NPN	-	35(2mm)	Tos	→2SC4666B
2SC4667	Si-NPN	Sw, 40V, 0,2A, 400MHz, 70/45nS	35a(2mm)	Toshiba	2SC4175..76
2SC4667-O	Si-NPN	-	35(2mm)	Tos	→2SC4667
2SC4667-R	Si-NPN	-	35(2mm)	Tos	→2SC4667
2SC4667-Y	Si-NPN	-	35(2mm)	Tos	→2SC4667
2SC4668	Si-NPN	Sw, Pow, Lo-sat, 60V, 7A, 10W, <300/2000nS	30j$	Shi	2SC4979, 2SD1804
2SC4669	Si-NPN	Sw, Pow, Lo-sat, 60V, 10A, 10W, <300/2000nS	30j$	Shi	-
2SC467	Si-NPN	GenP, 20V, 0,05A, 0,3W	2a$	Fui	BC168, BC183, BC238, BC548, 2SC1890+
2SC4670	Si-NPN	-	35(2mm)	Mat	→2SC4670
2SC4671	Si-N-Darl+Di	50V, 2A, 1W, B>1000	9c	Sanyo	-
2SC4672	Si-NPN	Lo-sat, 60/50V, 2A, 210MHz	39b	Rhm	2SC4521, 2SD1623..24, 2SC4409
2SC4672-P	Si-NPN	-	39	Rhm	→2SC4672
2SC4672-Q	Si-NPN	-	39	Rhm	→2SC4672
2SC4673	Si-NPN	UHF, 20V, 0,1A, 4500MHz	39b	Sanyo	2SC3357, 2SC4988
2SC4673-C	Si-NPN	-	39	Sanyo	→2SC4673
2SC4673-D	Si-NPN	-	39	Sanyo	→2SC4673
2SC4673-E	Si-NPN	-	39	Sanyo	→2SC4673
2SC4674	Si-NPN	UHF, 12V, 8mA, 6000MHz	35a(2mm)	Hit	BFR181W, BFS505, 2SC4899
2SC4675	Si-NPN	Sw, Pow, Lo-sat, 30V, 8A, 10W, 250MHz	14b	Sanyo	-
2SC4678	Si-NPN	HDTV Chroma-Out, 300V, 0,05A, 10W, 240MHz	17c	Tos	-
2SC4679	Si-NPN	=2SC4678: 8W	14b	Tos	2SC3789..90, (2SC3417, 2SC3503, 2SC4828)
2SC468(H)	Si-NPN	HF/Sw, 40V, 0,2A, 0,2W, 450MHz	4	Hit	BSS11, BSX19..20, 2N2368..69(A)..
2SC4680	Si-NPN	VHF/UHF, 12V, 50mA	3Sa	Hitachi	-
2SC4681	Si-NPN	Strobo, Lo-sat, 30V, 3A, 10W, 150MHz	30j$	Tos	2SC3074, 2SD1802, 2SD1805
2SC4682	Si-NPN	Hi-beta, Lo-sat, 30V, 3A, 0,9W, 150MHz	7c(9mm)	Tos	-
2SC4683	Si-NPN	=2SC4682: 1W	9c	Tos	-
2SC4684	Si-NPN	Hi-beta, Lo-sat, 50V, 5A, 10W, 150MHz	30j$	Tos	2SD1719, 2SD1755
2SC4685	Si-NPN	=2SC4684:	14b	Tos	-
2SC4686	Si-NPN	Dynamic Focus, 1500/1000V, 0,05A, 10W	17c	Tos	2SC4630, (2SC4578)
2SC4686A	Si-NPN	=2SC4686: 1500/1200V	17c	-	(2SC4578)

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2SC4687	Si-NPN	Sw,Pow,500/400V,7A,70W,30MHz	18j$	Mat	BUP22,TIP48A,2SC3040,2SC3089..
2SC4688	Si-NPN	AF-Pow,80V,6A,55W,30MHz	18c	Tos	2SC4385,2SC5099,2SD2064,(BD245A..F)
2SC4689	Si-NPN	AF-Out,120V,8A,70W,30MHz	18c	Tos	2SC4386,2SC5100,2SD2052,(BD245C..F)
2SC469	Si-NPN	FM-IF,20V,0,03A,250MHz	24b	Nec	(BF240,BF254,BF494,BF594,..)
2SC4690	Si-NPN	AF-Out,140V,10A,80W,30MHz	18c	Tos	2SC4387,2SC5101,2SC4886,(BD245D..F)
2SC4691	Si-NPN	-	35(1,6mm)	Mat	→2SC4691
2SC4691-Q	Si-NPN	-	35(1,6mm)	Mat	→2SC4691
2SC4691-R	Si-NPN	-	35(1,6mm)	Mat	→2SC4691
2SC4691-S	Si-NPN	-	35(1,6mm)	Mat	→2SC4691
2SC4692	Si-NPN	TV-HD,1500/800V,12A,50W	?18c	Hit	2SC5105,BU2525AF,BU4530AL
2SC4693	Si-NPN	VHF,30V,0,3A,0,9W,2500MHz	7c(9mm)	Hit	(2SC4308)
2SC4694	Si-NPN	-	35(2mm)	Sanyo	→2SC4694
2SC4695	Si-NPN	AF,Sw,Hi-Ueb,50V,0,5A,250MHz	35a(3mm)	Sanyo	-
2SC4696	Si-N-Darl+Di	80/80V,0,8A,1W,B>1000	9c	Sanyo	2SD1153,BC877,BC879,BSR51..52..
2SC4699K	Si-NPN	AF,Sw,25V,0,2A,250MHz,<50/40nS	35a	Rhm	2SC1621,2SC4894
2SC4699K-M	Si-NPN	-	35	Rhm	→2SC4699K
2SC4699K-N	Si-NPN	-	35	Rhm	→2SC4699K
2SC4699K-P	Si-NPN	-	35	Rhm	→2SC4699K
2SC47	Si-NPN	=2SC46:40V,0,72A	2a$	Fui	BFX55,BSW51..52,2N2218..19..
2SC470(-3..-6)	Si-NPN	HF/Vid,90..180V,0,1A,0,75W,150MHz	2a$	Son	BF257..259,BF657..659,2N5058..59
2SC4700	Si-NPN	=2SC4699K:	35a(2mm)	Rhm	2SC4175..76,2SC4755
2SC4700-M	Si-NPN	-	35(2mm)	Rhm	→2SC4700
2SC4700-N	Si-NPN	-	35(2mm)	Rhm	→2SC4700
2SC4700-P	Si-NPN	-	35(2mm)	Rhm	→2SC4700
2SC4702	Si-NPN	AF,Vid,300/300V,0,05A,80MHz	35a	Hit	BFN26,2SC4061,2SC4497
2SC4703	Si-NPN	UHF/CATV,25V,0,15A,6GHz	39b	Nec	-
2SC4703-SE	Si-NPN	-	39	Nec	→2SC4703
2SC4703-SF	Si-NPN	-	39	Nec	→2SC4703
2SC4703-SH	Si-NPN	-	39	Nec	→2SC4703
2SC4704	Si-NPN	Vid-Out,200/200V,0,2A,10W,300MHz	14h$	Hit	2SC3601
2SC4705	Si-NPN	Hi-beta,60V,0,2A,250MHz,B>800	39b	Sanyo	2SC3651
2SC4706	Si-NPN	Sw,Pow,900/600V,14A,130W,6MHz	18j$	Sak	BUV48(A),BUW13(A),BUW133(A)
2SC4707	Si-NPN	AF,Sw,35V,0,5A,0,8W,300MHz	7c(9mm)	Tos	2SC3939,2SC4414,2SD1211,2SD1937
2SC4708	Si-NPN	Display-Video,100V,0,2A,5W,1,1GHz	14h$	Hit	2SC3598,2SC3599
2SC4709	Si-NPN	TV,Dynamic Focus,2100/2100V,10mA	17j$	Sanyo	(2SC4476)
2SC471(H)	Si-NPN	GenP,30V,0,1A,0,2W,160MHz	2a	Hit	BC168,BC183,BC238,BC548,2SD767..
2SC4710(LS)	Si-NPN	=2SC4709:Iso	17c	Sanyo	(2SC4637)
2SC4713K	Si-NPN	HF/Sw,12V,0,05A,800MHz,Ron=2Ω	35a	Rohm	-
2SC4713K-Q	Si-NPN	-	35	Rhm	→2SC4713K
2SC4713K-R	Si-NPN	-	35	Rhm	→2SC4713K
2SC4713K-S	Si-NPN	-	35	Rhm	→2SC4713K
2SC4714	Si-NPN	CTV-Chroma,300/300V,0,1A,15W,140MHz	17j$	Mat	2SC1929
2SC4715	Si-NPN	GenP,LN,150V,0,05A,0,3W,160MHz	40c	Mat	2SC2362K,2SC2631..2632,2SC3800
2SC4716	Si-NPN	VHF-Osc,30V,0,05A,0,3W,>600MHz	40c	Mat	BF314,BF503,BF505,2SC1856,2SC3354
2SC4719	Si-NPN	GenP,-/32V,1A,0,9W	7c(9mm)	Rhm	2SC4145,2SD1207,2SD1292,2SD1616..
2SC472(H)	Si-NPN	=2SC471:180MHz,<100/500nS	2a	Hit	BC168,BC183,BC238,BC548,2N3904..
2SC4720	Si-NPN	GenP,-/150V,0,05A,0,8W	7c(9mm)	Rhm	BF298,BF422A,2SC3248,2SC3467
2SC4721	Si-NPN	AF-Dr/Out,-/50V,2A,0,9W	7c(9mm)	Rhm	2SC4145,2SD1207,2SD2485
2SC4722	Si-NPN	Vid/Sw,-/300V,0,1A,0,9W	7c(9mm)	Rhm	BF420A,2SC3468..69,2SC4166
2SC4723	Si-NPN	=2SC4642:	35a(2mm)	Rhm	2SC4081,2SC4128,2SC4155,2SC4177..
2SC4723-R	Si-NPN	-	35(2mm)	Rhm	→2SC4723
2SC4723-S	Si-NPN	-	35(2mm)	Rhm	→2SC4723
2SC4724	Si-N-Darl+Di	-/100V,3A,1,2W,B>2000	78b	Sanyo	2SC4339
2SC4725(H)	Si-NPN	=2SC3837K:	35a(1,6mm)	Rhm	-
2SC4725-L	Si-NPN	-	35(1,6mm)	Rhm	→2SC4725
2SC4725-M	Si-NPN	-	35(1,6mm)	Rhm	→2SC4725
2SC4725-N	Si-NPN	-	35(1,6mm)	Rhm	→2SC4725
2SC4726(H)	Si-NPN	=2SC3838K:	35a(1,6mm)	Rhm	-
2SC4726-L	Si-NPN	-	35(1,6mm)	Rhm	→2SC4726
2SC4726-M	Si-NPN	-	35(1,6mm)	Rhm	→2SC4726
2SC4726-N	Si-NPN	-	35(1,6mm)	Rhm	→2SC4726
2SC4727	Si-NPN	Lo-sat,30V,8A,250MHz,30/265nS	?12b	Sanyo	-
2SC4728	Si-NPN	Sw,Pow,60V,5A,180MHz,50/520nS	?12b	Sanyo	-
2SC4729	Si-NPN	Sw,Pow,60V,8A,180MHz,50/520nS	?12b	Sanyo	-

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2SC473(H)	Si-NPN	=2SC471:70V,180MHz,<80/200nS	2a	Hit	BC174,BC182,BC190,BC546,2N2222A+
2SC4730	Si-NPN	Sw,Pow,120V,3A,180MHz,100/950nS	?12b	Sanyo	-
2SC4731	Si-NPN	Sw,Pow,120V,4A,180MHz,100/950nS	?12b	Sanyo	-
2SC4732	Si-NPN	=2SC3416:	?12b	Sanyo	(2SC3502,2SC3955,2SC3600..01,2SC3788)
2SC4733	Si-NPN	=2SC3417:	?12b	Sanyo	(2SC3417,2SC3503,2SC3789..90,2SC4828)
2SC4734	Si-NPN	Sw,400/400V,2A,1,5W,60MHz	?12b	Sanyo	-
2SC4735	Si-NPN	AM/FM-E,27MHz-CB,75V,1A,250MHz,PQ>1W(27MHz,12V)	?12b	Sanyo	-
2SC4736	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,80V,2A,170MHz,B>800,230/3450nS	?12b	Sanyo	(2SC3474,2SD1755)
2SC4737	Si-N-Darl+Di	Z-Di(B→C),60±10V,2A,180MHz,B>1000,200/4000nS	?12b	Sanyo	(BD677,BD679,2SD1759,2SD1817,++)
2SC4738	Si-NPN	AF,LN,60V,0,15A,>80MHz	35a(1,6mm)	Toshiba	2SC4617,2SD2216
2SC4738-BL	Si-NPN	-	35(1,6mm)	Tos	→2SC4738
2SC4738F	Si-NPN	AF,LN,60V,0,15A,>80MHz	flat	Tos	2SC4617,2SD2216
2SC4738-GR	Si-NPN	-	35(1,6mm)	Tos	→2SC4738
2SC4738-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC4738
2SC474(H)	Si-NPN	=2SC471:70V,<100/500nS	2a	Hit	BC174,BC182,BC190,BC546,2N2222A+
2SC4740	Si-NPN	CTV/Display-HD,1500/800V,8A,50W	23a$	Hitachi	BU508A,BU2508A,2SC3027..28,2SC4801..
2SC4741	Si-NPN	CTV/Display-HD,1500/800V,10A,50W	23a$	Hitachi	BU2520A,2SC3688
2SC4742	Si-NPN+Diode	Display-HD,1500V,6A,50W	18j$	Hit	BU2508D,2SC3482,2SC3682,2SC4292
2SC4743	Si-NPN	Display-HD,1500/800V,6A,50W	18j$	Hit	BU2508A,BU4508AX,BU908,2SC3486,2SC3686
2SC4744	Si-NPN+Diode	=2SC4742:Iso	?18c	Hit	BU2508DF,BU4508DF,2SC4294,2SC4764,2SD1652
2SC4745	Si-NPN	=2SC4743:Iso	?18c	Hit	BU2508AF,BU4515AF,2SC3884A,2SC3894,2SC4830
2SC4746(A)	Si-NPN	=2SC4740:Iso	?18c	Hit	BU2508AF,2SC3886A,2SC3896,2SC4758
2SC4747	Si-NPN	=2SC4741:Iso	?18c	Hit	BU2520AF,BU4540AL,2SC4542,2SC4589
2SC475	Si-NPN	=2SC476:ra	24b	Nec	(BC169,BC184,BC239,BC549,2SC2675,..)
2SC4750	Si-NPN	Sw,Pow,500/400V,15A,80W,<500/1650nS	-	Fjd	-
2SC4754	Si-NPN	Sw,Pow,600/400V,2A,20W,<1/3,5µS	30j$	Tos	2SC4171,2SC4221,(BUT93,BUX84,+)
2SC4755	Si-NPN	Fast-Sw,25V,0,2A,500MHz,17/15nS	35a(2mm)	Matsushita	2SC4175..76,2SC4452
2SC4755-P	Si-NPN	-	35(2mm)	Mat	→2SC4755
2SC4755-Q	Si-NPN	-	35(2mm)	Mat	→2SC4755
2SC4755-R	Si-NPN	-	35(2mm)	Mat	→2SC4755
2SC4757	Si-NPN	Display-HD,Hi-res,1500/600V,7A,50W	18c	Tos	2SC3885A,2SC3895,BU4515AX
2SC4758	Si-NPN	Display-HD,Hi-res,1500/600V,8A,50W	18c	Tos	2SC3886A,2SC3896,BU4522AX
2SC4759	Si-NPN	Display-HD,Hi-res,1500/600V,10A,50W	18c	Tos	BU2520AF,BU4525AX,BUH715,2SC4542
2SC476	Si-NPN	Min,AF-Dr,20V,0,1A,0,15W,100MHz	24b	Nec	(BC168,BC183,BC238,BC548,2SD767,..)
2SC4760	Si-NPN	Display-HD,Hi-res,2000/800V,8A,200W	77j$	Tos	-
2SC4761	Si-NPN	Display-HD,Hi-res,1700/600V,6A,50W	18c	Tos	BUH417,BUH517,2SC4806
2SC4762	Si-NPN+Diode	Display-HD,VGA,1500/600V,±7A,50W	18c	Tos	2SC3892A,2SC4123,2SC4916,BU4508DX
2SC4763	Si-NPN+Diode	Display-HD,VGA,1500/600V,±8A,50W	18c	Tos	BU2520DF,BU4522DX,2SC3893A,2SC4124
2SC4764	Si-NPN+Diode	Display-HD,VGA,1500/600V,±6A,50W	18c	Tos	2SC3892A,2SC4294,2SC4122,BU4507DX
2SC4765	Si-NPN+Diode	Display-HD,VGA,1700/600V,±5A,50W	18c	Tos	BUH517D,2SC4962,2SD2253
2SC4766	Si-NPN+Diode	Display-HD,VGA,1700/600V,±6A,50W	18c	Tos	BU2720DX,BUH517D,2SC4962
2SC4767	Si-NPN	VHF-Dr/Out,36V,0,3A,1W,>1500MHz	7c(9mm)	Mat	-
2SC4768	Si-NPN	Sw,Pow,450/400V,10A,80W,<1/3µS	18j$	Tos	2SC2625,2SC2740,2SC3042,2SC4138..
2SC4769	Si-NPN+Diode	=2SC4770:Int.Damper-Diode	18c	Sanyo	BU2508DF,BU4508DX,2SC3892A,2SC4123,2SC4916
2SC477	Si-NPN	HF,50V,0,03A,0,14W,230MHz	2a$	Mat,Mic	BF240..241,BF254..255,BF594..595,..
2SC4770	Si-NPN	Monitor-HD,Hi-def,1500/800,7A,60W	18c	Sanyo	BU4508AX,2SC3885A,2SC3895,2SC4757,2SD2252
2SC4771K	Si-NPN	HF,30V,0,05A,600MHz	35a	Rohm	BF599,BF799,2SC3130,2SC3374,..
2SC4771K-L	Si-NPN	-	35	Rhm	→2SC4771K
2SC4771K-M	Si-NPN	-	35	Rhm	→2SC4771K
2SC4771K-N	Si-NPN	-	35	Rhm	→2SC4771K
2SC4771K-P	Si-NPN	-	35	Rhm	→2SC4771K
2SC4772	Si-NPN	=2SC4771K:	35a(2mm)	Rhm	BF547W,BFS17W,2SC3932,2SC3935
2SC4772-L	Si-NPN	-	35(2mm)	Rhm	→2SC4772
2SC4772-M	Si-NPN	-	35(2mm)	Rhm	→2SC4772
2SC4772-N	Si-NPN	-	35(2mm)	Rhm	→2SC4772
2SC4772-P	Si-NPN	-	35(2mm)	Rhm	→2SC4772
2SC4773	Si-NPN	=2SC4326LK:	35a(2mm)	Rhm	BFS47W,BFS17W,2SC3933,2SC4780
2SC4773-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4773
2SC4773-R	Si-NPN	-	35(2mm)	Rhm	→2SC4773
2SC4773-S	Si-NPN	-	35(2mm)	Rhm	→2SC4773
2SC4774	Si-NPN	=2SC4713K:	35a(2mm)	Rhm	-
2SC4774-Q	Si-NPN	-	35(2mm)	Rhm	→2SC4774
2SC4774-R	Si-NPN	-	35(2mm)	Rhm	→2SC4774
2SC4774-S	Si-NPN	-	35(2mm)	Rhm	→2SC4774

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2SC4775	Si-NPN	=2SC4642: 0,4W	9c	Rhm	BC167, BC182, BC237, BC547, 2SD767..
2SC4776M	Si-NPN	=2SC4642: 0,4W	9c	Rhm	BC167, BC182, BC237, BC547, 2SD767..
2SC4777	Si-NPN	=2SC4642: 0,4W, PinS=14mm	9c	Rhm	BC167, BC182, BC237, BC547..
2SC4778	Si-NPN	=2SC4642: 0,4W, PinS=14mm	9c	Rhm	BC167, BC182, BC237, BC547, 2SD767..
2SC4779S	Si-NPN	=2SC4642: 0,3W	41c	Rhm	BC167, BC182, BC237, BC547, 2SD767..
2SC478	Si-NPN	GenP, 50V, 0,12A, 0,3W, 180MHz	2a$	Mat	BC167, BC182, BC237, BC547, 2SD767..
2SC4780	Si-NPN	UHF, 25V, 50mA, 4500MHz	35a(2mm)	Mat	2SC4571, 2SC4905..06, 2SC5110
2SC4780-B	Si-NPN	-	35(2mm)	Mat	→2SC4780
2SC4780-C	Si-NPN	-	35(2mm)	Mat	→2SC4780
2SC4781	Si-NPN	Strobo, Lo-sat, 30V, 4A, 0,9W, 170MHz	7c(9mm)	Tos	2SC4482, 2SD1145
2SC4782	Si-NPN	-	35	Mat	→2SC4782
2SC4782-P	Si-NPN	-	35	Mat	→2SC4782
2SC4782-Q	Si-NPN	-	35	Mat	→2SC4782
2SC4782-R	Si-NPN	-	35	Mat	→2SC4782
2SC4783	Si-NPN	AF, 60V, 0,1A, 150MHz	35a(1,6mm)	Nec	2SC4738, 2SC4617
2SC4783-L4	Si-NPN	-	35(1,6mm)	Nec	→2SC4783
2SC4783-L5	Si-NPN	-	35(1,6mm)	Nec	→2SC4783
2SC4783-L6	Si-NPN	-	35(1,6mm)	Nec	→2SC4783
2SC4783-L7	Si-NPN	-	35(1,6mm)	Nec	→2SC4783
2SC4784	Si-NPN	VHF/UHF, 15V, 20mA, 10GHz	35a(2mm)	Hitachi	BFS505, 2SC5095
2SC4786	Si-NPN	Sw, Pow, 900/500V, 5A, 40W, >20MHz	18c	Fjd	BUW11AF, 2SC3400, 2SC4427, 2SC4586..
2SC4787	Si-NPN	TV-IF, 45V, 50mA, 0,6W, >300MHz	9c	Mat	BF921S, BF959
2SC4789	Si-NPN	Display-HD, 1500/800V, 25A, 150W	77j$	Hit	2SC3998, 2SC4290A, BU4550AL
2SC479(H)	Si-NPN	Sw, 60V, 0,6A, 0,65W, 30/55nS	2a$	Hit	BSS13, BSV77, 2N5189, 2SC1072..
2SC4791	Si-NPN	-	44	Hit	→2SC4791
2SC4792	Si-NPN	VHF, 30V, 50mA, 800MHz	35a	Mat	BF799, 2SC3015, 2SC3374
2SC4793	Si-NPN	AF-Pow, 230/230V, 1A, 20W, 100MHz	17c	Tos	-
2SC4795	Si-NPN	Sw, Pow, 500/400V, 30A, 120W, <1/3?	18j$	Fjd	-
2SC4796	Si-NPN	Display-HD, 1700/900V, 6A, 50W	?18c	Hit	BUH417, 2SC4796
2SC4797	Si-NPN	Display-HD, 1700/900V, 8A, 50W	?18c	Hit	BUH517
2SC4799	Si-NPN	Sw, Pow, 300/80V, 6A, 50W	18j$	Hit	TIP55A..57A, 2SC2305, 2SC3813
2SC48	Si-NPN	=2SC46: 120V	2a$	Fui	BSW67..68, BSY55..56, 2N1893..
2SC480	Si-NPN	=2SC479: 0,8W, <30/40nS	2a$	Hit	BSS13, BSV77, 2N5189, 2SC1072..
2SC4800	Si-NPN	Sw, Pow, HD, 1500/800V, 5A, 80W	23a$	Hit	BU208A, BU2508A, 2SD1496, 2SC3685..
2SC4801	Si-NPN	Display-HD, 1500/500V, 8A, 50W	23a$	Hit	BU908, BU2508A, 2SC3687, 2SC3896..
2SC4802	Si-NPN	Display-HD, 1700/800V, 5A, 50W	23a$	Hitachi	2SC3026, 2SD784..85, 2SD1434
2SC4803	Si-NPN+Diode	Display-HD, 1500/800V, 5A, 50W	23a$	Hitachi	BU208D, BU2508D, 2SD1171..75, 2SC3481..
2SC4804	Si-NPN	Sw-Reg, 900/600V, 3A, 30W, <300/4500nS	15c	Shi	2SC3559, 2SC4304, 2SC4517, 2SC4908
2SC4805	Si-NPN	UHF, 15V, 65mA, >7GHz	35a(2mm)	Mat	BFS520, 2SC4901, 2SC5051
2SC4806	Si-NPN	Display-HD, Hi-res, 1700/600V, 5A, 50W	18c	Tos	BUH417, BUHS17, 2SC4761
2SC4807	Si-NPN	VHF/UHF, 20V, 0,2A, 4,4GHz	39b	Hit	-
2SC4808	Si-NPN	-	35(1,6mm)	Mat	→2SC4808
2SC4809	Si-NPN	-	35(1,6mm)	Mat	→2SC4809
2SC481	Si-NPN	AM/FM-Dr/Out, 60V, 1A, Pq>1W(50MHz)	2a$	Tos	BFS23, BLY34
2SC4810	Si-N-Darl+Di	Sw, Pow, 100V, ±5A, 500/3100nS, B>2000	78c	Nec	-
2SC4811	Si-N-Darl+Di	Sw, Pow, 100V, ±8A, 500/3100nS, B>2000	78c	Nec	-
2SC4812	Si-N-Darl+Di	Sw, Pow, 100V, ±10A, 500/3100nS, B>2000	78c	Nec	-
2SC4813	Si-NPN+Diode	=2SC4553: 1,8W	78c	Nec	-
2SC4814	Si-NPN+Diode	Hi-beta;lo-sat, 100V, ±2,5A, 500/2500nS	78c	Nec	-
2SC4815	Si-NPN	Lo-sat, 100V, 5A, 1,8W, 100/1250nS	78c	Nec	-
2SC4816	Si-NPN	Lo-sat, 100V, 7A, 1,8W, 200/1400nS	78c	Nec	-
2SC4817	Si-NPN	Lo-sat, 150V, 5A, 1,8W, <300/1900nS	78c	Nec	-
2SC4818	Si-NPN	Lo-sat, 150V, 7A, 1,8W, <300/1900nS	78c	Nec	-
2SC4819	Si-NPN	Lo-sat, 150V, 10A, 1,8W, <300/1900nS	78c	Nec	-
2SC482	Si-NPN	HF/GenP, 40V, 0,6A, 0,6W, >50MHz	2a$	Tos	BC140..141, BC300..302, 2N2218..19..
2SC4820	Si-NPN	Sw-Reg, 900/450V, 6A, 30W, <500/3800nS	17c	Sak	BUT12(A)F, BUT18(A)F, BUV46(A)FI
2SC4821	Si-NPN	=2SC3950: 1,3W	?12b	Sanyo	(→2SC3950)
2SC4822	Si-NPN	=2SC3951: 1,3W	?12b	Sanyo	(→2SC3951)
2SC4823	Si-NPN	=2SC3952: 1,3W	?12b	Sanyo	(→2SC3952)
2SC4824	Si-NPN	=2SC3953: 1,3W	?12b	Sanyo	(→2SC3953)
2SC4825	Si-NPN	=2SC3954: 1,3W	?12b	Sanyo	(→2SC3954)
2SC4826	Si-NPN	=2SC3955: 1,3W	?12b	Sanyo	(→2SC3955)
2SC4827	Si-NPN	=2SC3956: 1,3W	?12b	Sanyo	(→2SC3956)
2SC4828	Si-NPN	TV-Video, 300/300V, 0,1A, 8W, 80MHz	14b	Hit	2SC3271, 2SC4217, (BF417, BF459)

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2SC4829	Si-NPN	Display-Video,100V,0,2A,0,9W,1,1GHz	7c(9mm)	Hit	2SC5225
2SC483	Si-NPN	AF,Sw-Pow,100V,1A,15W,25MHz	22a$	Tos	BD239C,BD241C,2SC1913,2SC2275..
2SC4830	Si-NPN	Display-HD,Hi-res,1500/600V,6A,50W	18c	Tos	2SC3884A,2SC3894,2SC4757,BU4508AX
2SC4831	Si-NPN	Sw,Pow,500/400V,15A,80W,<500/1650nS	18c	Fjd	2SC4298,2SC4424
2SC4833	Si-NPN	Sw,Pow,500/400V,5A,35W,<300/1400nS	15c	Shi	BUT11(A)F,2SC4054,2SC4073,2SC4371,..
2SC4834	Si-NPN	Sw,Pow,500/400V,8A,45W,<300/1400nS	15c	Shi	BU306F,BUT12(A)F,2SC4130,2SC4161,..
2SC4835	Si-NPN	-	35(2mm)	Mat	→2SC4835
2SC4836	Si-NPN	Sw,Pow,60/20V,5A,1,5W,120MHz	?12b	Sanyo	2SD1903
2SC4837	Si-NPN	Sw,Pow,60/50V,4A,1,5W,150MHz	?12b	Sanyo	2SD1903
2SC4838	Si-NPN	UHF-Out,50V,2A,Pq>6W(1650MHz)	-	Mit	-
2SC4839	Si-NPN	-	35(1,6mm)	Tos	→2SC4839
2SC484	Si-NPN	GenP,150V,1,5A,0,8W,20MHz	2a$	Tos	BSS43,BSW68,2SC1860
2SC4840	Si-NPN	-	35(1,6mm)	Tos	→2SC4840
2SC4841	Si-NPN	-	35(1,6mm)	Tos	→2SC4841
2SC4842	Si-NPN	-	44(2mm)	Tos	→2SC4842
2SC4843	Si-NPN	-	44(2mm)	Tos	→2SC4843
2SC4844	Si-NPN	-	44(2mm)	Tos	→2SC4844
2SC4845	Si-NPN	Pow,Lo-sat,-/120V,5A,40W	17j$	Rhm	2SC4328
2SC4846	Si-NPN	=2SC4845:Iso,30W	17c	Rhm	2SD1270
2SC4847	Si-NPN	Pow,Lo-sat,-/120V,5A,60W	16c	Rhm	(2SD2065)
2SC4848	Si-NPN	Sw-Reg,lo-sat,250/120V,7A,40W,20MHz	17j$	Rhm	-
2SC4849	Si-NPN	=2SC4848:Iso,30W	17c	Rhm	-
2SC485	Si-NPN	=2SC484:100V	2a$	Tos	BCX40,BSW66,BSX46,2N3107..08..
2SC4850	Si-NPN	Pow,Lo-sat,-/120V,7A,60W	16c	Rhm	(2SD2065)
2SC4851	Si-NPN	-	35(2mm)	Sanyo	→2SC4851
2SC4852	Si-NPN	Hi-beta,25V,0,1A,240MHz,Ron=0,9Ω	35a	Sanyo	-
2SC4853	Si-NPN	VHF/UHF,12V,15mA,5GHz	35a(2mm)	Sanyo	BFR92W,BFR820W
2SC4853-3	Si-NPN	-	35(2mm)	Sanyo	→2SC4853
2SC4853-4	Si-NPN	-	35(2mm)	Sanyo	→2SC4853
2SC4853-5	Si-NPN	-	35(2mm)	Sanyo	→2SC4853
2SC4854	Si-NPN	-	35	Sanyo	→2SC4854
2SC4854-3	Si-NPN	-	35	Sanyo	→2SC4854
2SC4854-4	Si-NPN	-	35	Sanyo	→2SC4854
2SC4854-5	Si-NPN	-	35	Sanyo	→2SC4854
2SC4855	Si-NPN	-	44	Sanyo	→2SC4855
2SC4855-3	Si-NPN	-	44	Sanyo	→2SC4855
2SC4855-4	Si-NPN	-	44	Sanyo	→2SC4855
2SC4855-5	Si-NPN	-	44	Sanyo	→2SC4855
2SC4856	Si-NPN	=2SC4859:	35a(2mm)	Sanyo	2SC3937
2SC4857	Si-NPN	=2SC4859:	35a(3mm)	Sanyo	2SC3704,2SC3445
2SC4858	Si-NPN	=2SC4859:	44ze	Sanyo	2SC4092
2SC4859	Si-NPN	VHF/UHF,18V,80mA,5,5GHz	39b	Sanyo	BFQ193,2SC3607
2SC486	Si-NPN	=2SC484:70V	2a$	Tos	BCX40,BSW65,BSX45,2N3109..10..
2SC4860	Si-NPN	UHF-Osc,20V,30mA,6,5GHz	35a(2mm)	Sanyo	2SC3937
2SC4860-3	Si-NPN	-	35(2mm)	Sanyo	→2SC4860
2SC4860-4	Si-NPN	-	35(2mm)	Sanyo	→2SC4860
2SC4860-5	Si-NPN	-	35(2mm)	Sanyo	→2SC4860
2SC4861	Si-NPN	-	35	Sanyo	→2SC4861
2SC4861-3	Si-NPN	-	35	Sanyo	→2SC4861
2SC4861-4	Si-NPN	-	35	Sanyo	→2SC4861
2SC4861-5	Si-NPN	-	35	Sanyo	→2SC4861
2SC4862	Si-NPN	-	44	Sanyo	→2SC4862
2SC4862-3	Si-NPN	-	44	Sanyo	→2SC4862
2SC4862-4	Si-NPN	-	44	Sanyo	→2SC4862
2SC4862-5	Si-NPN	-	44	Sanyo	→2SC4862
2SC4863	Si-NPN	VHF/UHF,16V,70mA,7GHz	35a(2mm)	Sanyo	BFS520,2SC5085
2SC4863-3	Si-NPN	-	35(2mm)	Sanyo	→2SC4863
2SC4863-4	Si-NPN	-	35(2mm)	Sanyo	→2SC4863
2SC4863-5	Si-NPN	-	35(2mm)	Sanyo	→2SC4863
2SC4864	Si-NPN	-	35	Sanyo	→2SC4864
2SC4864-3	Si-NPN	-	35	Sanyo	→2SC4864
2SC4864-4	Si-NPN	-	35	Sanyo	→2SC4864
2SC4864-5	Si-NPN	-	35	Sanyo	→2SC4864
2SC4865	Si-NPN	-	44	Sanyo	→2SC4865

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2SC4865-3	Si-NPN	-	44	Sanyo	→2SC4865
2SC4865-4	Si-NPN	-	44	Sanyo	→2SC4865
2SC4865-5	Si-NPN	-	44	Sanyo	→2SC4865
2SC4866	Si-NPN	VHF/UHF,18V,70mA,6,5GHz	39b	Sanyo	BFQ193,2SC3301,2SC3607
2SC4867	Si-NPN	VHF/UHF,16V,50mA,9GHz	35a(2mm)	Sanyo	2SC4593,2SC4901
2SC4867-3	Si-NPN	-	35(2mm)	Sanyo	→2SC4867
2SC4867-4	Si-NPN	-	35(2mm)	Sanyo	→2SC4867
2SC4867-5	Si-NPN	-	35(2mm)	Sanyo	→2SC4867
2SC4868	Si-NPN	-	35	Sanyo	→2SC4868
2SC4868-3	Si-NPN	-	35	Sanyo	→2SC4868
2SC4868-4	Si-NPN	-	35	Sanyo	→2SC4868
2SC4868-5	Si-NPN	-	35	Sanyo	→2SC4868
2SC4869	Si-NPN	-	44	Sanyo	→2SC4869
2SC4869-3	Si-NPN	-	44	Sanyo	→2SC4869
2SC4869-4	Si-NPN	-	44	Sanyo	→2SC4869
2SC4869-5	Si-NPN	-	44	Sanyo	→2SC4869
2SC487	Si-NPN	AF,Sw-Pow,110V,1,5A,15W,20MHz	22a$	Tos	BD239C,BD241C,2SC2275,2SC2528..
2SC4870	Si-NPN	=2SC4867:8GHz	39b	Sanyo	2SC4643
2SC4871	Si-NPN	VHF/UHF,16V,20mA,10GHz	35a(2mm)	Sanyo	BFS505,2SC5095
2SC4871-3	Si-NPN	-	35(2mm)	Sanyo	→2SC4871
2SC4871-4	Si-NPN	-	35(2mm)	Sanyo	→2SC4871
2SC4871-5	Si-NPN	-	35(2mm)	Sanyo	→2SC4871
2SC4872	Si-NPN	=2SC4871:	35a	Sanyo	BFR505,2SC5094
2SC4873	Si-NPN	=2SC4871:	44ze	Sanyo	2SC5097
2SC4874	Si-NPN	VHF/UHF,20V,50mA,5,8GHz	7f	Hit	2SC3512,2SC4629
2SC4875	Si-NPN	VHF/UHF,15V,50mA,8,5GHz	7f	Hit	2SC4629
2SC4876	Si-NPN	Sw,Pow,Lo-sat,60V,30A,45W,<0,3/2µS	15c	Shi	-
2SC4877	Si-NPN+Diode	TV/Monitor-HD,1500V,8A,50W	?18c	Hit	BU2508DF,BU4523DF,2SC3893A,2SC4763,2SD2371,..
2SC4878	Si-NPN+Diode	TV/Monitor-HD,1500V,10A,50W	?18c	Hit	BU2520DF,2SC4125,2SC4531,2SD1881
2SC4879	Si-NPN	TV/Monitor-HD,1700/900V,10A,50W	?18c	Hit	BU2722AF,2SC5150
2SC487A	Si-NPN	=2SC487:150V	22a$	-	BD239D,2SC2275A,2SC2344,2SC2529..
2SC488	Si-NPN	AF,Sw-Pow,140V,3A,16W,10MHz	22a$	Tos	BD241D,BDV11,2SC2516,2SD772..
2SC4880	Si-NPN	TV/Monitor-HD,1700/900V,12A,100W	77j$	Hit	2SC4896,BU4730AL
2SC4881	Si-NPN	Sw,Pow,Lo-sat,60V,5A,20W,100/900nS	17c	Tos	2SC3299,2SC3746,2SC4549,2SC4596
2SC4882	Si-NPN	Sw,Pow,Lo-sat,1200V,5A,60W,<2/4µS	16c	Mat	2SC4584
2SC4883	Si-NPN	TV,AF-Pow,150/150V,2A,20W,120MHz	17c	Sak	2SC3298,2SC3364,2SC4159,2SD1763A
2SC4883A	Si-NPN	=2SC4883:180/180V	17c	-	2SC3298A..B,2SC4159
2SC4884	Si-NPN	Vid-Out,300/300V,0,1A,1,5W,70MHz	?12b	Sanyo	(2SC1505..07,2SC3952,2SC3945,2SC4075)
2SC4885	Si-NPN	UHF-Osc,25V,50mA,3,5GHz	35a(2mm)	Nec	2SC4780,2SC4905..06,2SC5110
2SC4886	Si-NPN	AF,Sw-Pow,150/150V,14A,80W,60MHz	18c	Sak	2SC4388
2SC4887	Si-NPN	CRT-Display,2500/1200V,0,1A	17c	Sanyo	-
2SC4888	Si-NPN	CRT-Display,2500/1200V,0,3A	17c	Sanyo	-
2SC489	Si-NPN	=2SC488:100V	22a$	Tos	BD241C,BD243C,BD539C,BD937..
2SC4890	Si-NPN	CRT HD,Hi-res,1500/800V,12A,75W	18c	Sanyo	BU2525AF,BU2527AF,BU4540AL,2SC5105
2SC4891	Si-NPN	CRT HD,Hi-res,1500/800V,15A,100W	18c	Sanyo	2SC5252,BU4540AL
2SC4892	Si-NPN	Sw,Pow,900/800V,1A,15W,4MHz,<1/4µS	78c	Mat	(BUX85F,2SC3794A,2SC3978)
2SC4893	Si-NPN	VHF-Out,-/16V,0,3A,Pq>0,6W(175MHz)	78	Mat	-
2SC4894	Si-NPN	Fast-Sw,25V,0,13A,500MHz,17/15nS	35a	Matsushita	2SC1621,2SC4453
2SC4895	Si-N-Darl+Di	AF-Pow,120/100V,3/5A,30W,80MHz,B>2000	17c	Rhm	2SD1785,2SD2014..2015
2SC4896	Si-NPN	TV/Monitor-HD,1700/900V,15A,100W	77j$	Hit	-
2SC4897	Si-NPN	TV/Monitor-HD,1500/800V,20A,150W	77j$	Hit	2SC3997,2SC4290A,2SD2356,BU4550AL
2SC4898	Si-NPN	Sw,Pow,1000/300V,5A,40W,8MHz,<1,5/4µS	17c	Mat	BUT11AF,BUT18AF,BUV46AFI,2SC4518A
2SC4899	Si-NPN	VHF/UHF,15V,20mA,9GHz	35a(2mm)	Hitachi	BFS505,2SC5095
2SC49(M,N)	Si-NPN	HF/Sw,120V,0,3A,0,8W,160MHz	2a$	Nec	BSW67..68,BSY55..56,2N1893..
2SC490	Si-NPN	=2SC488:60V	22a$	Tos	BD241A,BD243A,BD539A,BD935..
2SC4900	Si-NPN	VHF/UHF,15V,50mA,9GHz	44ze	Hit	2SC4094,2SC4127
2SC4901	Si-NPN	-	35(2mm)	Hit	→2SC4901
2SC4902	Si-NPN	VHF/UHF,20V,30mA,6GHz	35a	Hitachi	BFR182,2SC3011,2SC5106
2SC4903	Si-NPN	-	35(2mm)	Hit	→2SC4903
2SC4904	Si-NPN	VHF/UHF,20V,50mA,5,8GHz	35a	Hitachi	BF770A,BFQ67,BFR183,2SC3513
2SC4905	Si-NPN	-	35(2mm)	Hit	→2SC4905
2SC4906	Si-NPN	-	35(2mm)	Hit	→2SC4906
2SC4907	Si-NPN	Sw-Reg,600/500V,6A,30W,8MHz,<1/5µS	17c	Sak	BU306F,BUT22BF..CF,2SC4056,2SC4546
2SC4908	Si-NPN	Sw-Reg,900/800V,3A,35W,6MHz,<1/6µS	17c	Sak	2SC3559,2SC4304,2SC4517,2SC4471A,..

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2SC4909	Si-NPN	Muting,Hi-Ueb,25V,0,1A	35a(2mm)	Sanyo	-
2SC491	Si-NPN	AF,Sw-Pow,50V,1,5A,15W,40MHz	22a$	Tos	BD239,BD241,2SC1398,2SC3252..
2SC4910	Si-NPN	VHF-Dr,38V,0,75A,Pq=0,9W(175MHz)	?12b	Sanyo	-
2SC4911K	Si-NPN	Sw,20V,0,2A,450MHz	35a(3mm)	Rohm	2SC3735,2SC4453
2SC4912	Si-NPN	=2SC4911K:	35a(2mm)	Rhm	2SC4175..76,2SC4452
2SC4913	Si-NPN	Sw,Pow,2000/2000V,20mA,B>10	17j$	Hit	-
2SC4915	Si-NPN	=2SC2714:	35a(1,6mm)	Tos	2SC4655,2SC5021
2SC4915-O	Si-NPN	-	35(1,6mm)	Tos	→2SC4915
2SC4915-R	Si-NPN	-	35(1,6mm)	Tos	→2SC4915
2SC4915-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC4915
2SC4916	Si-NPN+Diode	Display-HD,Hi-res,1500/600V,n7A,50W	18c	Tos	2SC3892A,2SC4762,BU4508DX
2SC4917	Si-NPN	Sw-Reg,600/400V,2A,10W,<1/3,5µS	14b	Rhm	(2SC3924)
2SC4918	Si-NPN	HF,FM,40V,0,05A,750MHz	35a(1,6mm)	Sanyo	2SC4809,2SC4915,2SC5021
2SC4919	Si-NPN	-	35(1,6mm)	Sanyo	→2SC4919
2SC492	Si-NPN	AF,Sw-Pow,110V,5A,50W	23a$	Tos	BD245C,BDV95,2N5759..60,2SD718..
2SC4920	Si-NPN-Digital	Muting,25V,0,1A,240MHz,Ron=2,2Ω,R1=R2=4,7kΩ	35a(1,6mm)	Sanyo	DTC143EE,RN1101,UN921L
2SC4921	Si-NPN-Digital	Muting,25V,0,1A,240MHz,Ron=2,8Ω,R1=R2=10kΩ	35a(1,6mm)	Sanyo	DTC114EE,RN1102,UN9211
2SC4922	Si-NPN-Digital	Muting,25V,0,1A,240MHz,Ron=4Ω,R1=R2=47kΩ	35a(1,6mm)	Sanyo	DTC144EE,RN1104,UN9213
2SC4923	Si-NPN	CRT HD,Hi-res,1500/800V,8A,70W	18c	Sanyo	BU2520AF,BU4522AX,2SC3896,2SC3886A,2SC4758,..
2SC4924	Si-NPN	CRT HD,Hi-res,1500/800V,10A,70W	18c	Sanyo	BU2520AF,BU4522AX,BUH715,2SC4542,2SC4759
2SC4926	Si-NPN	VHF/UHF,15V,50mA,11GHz	44ze	Hit	2SC4094,2SC4127,2SC4592
2SC4927	Si-NPN+Diode	TV/Monitor-HD,1500V,8A,50W	?18c	Hit	BU2508DF,BU4522DF,2SC3893A,2SC4763,2SD2371,..
2SC4928	Si-NPN	Monitor-HD,1500/800V,15A,150W	77j$	Hit	2SC3996,2SC4289A,BU4550AL
2SC4929	Si-NPN	Sw,500/400V,0,8A,80MHz	39b	Mat	-
2SC493	Si-NPN	=2SC492:80V	23a$	Tos	BD245B,BDV93,2N4915,2SD985..986..
2SC4930	Si-NPN	VHF/UHF,7GHz	35a(1,6mm)	Sanyo	-
2SC4931	Si-NPN	VHF/UHF,16V,0,05A,9GHz	35a(1,6mm)	Sanyo	2SC5139
2SC4932	Si-NPN	SMD	35a(2mm)	Hit	-
2SC4932-B	Si-NPN	-	35(2mm)	Hit	→2SC4932
2SC4932-C	Si-NPN	-	35(2mm)	Hit	→2SC4932
2SC4932-D	Si-NPN	-	35(2mm)	Hit	→2SC4932
2SC4933	Si-NPN	SMD	35a(2mm)	Hit	-
2SC4933-D	Si-NPN	-	35(2mm)	Hit	→2SC4933
2SC4933-E	Si-NPN	-	35(2mm)	Hit	→2SC4933
2SC4933-F	Si-NPN	-	35(2mm)	Hit	→2SC4933
2SC4934	Si-NPN	=2SC4046:Iso	14b	Hit	2SC3953,(2SC3598..99,2SC4046)
2SC4935	Si-NPN	Pow,50V,3A,10W,80MHz	17c	Tos	2SC3299,2SC3690,2SC3746,2SD1762
2SC4937	Si-NPN	=2SC3968:35W	30j$	Rhm	-
2SC4938	Si-NPN	Sw,Pow,400/400V,5A,35W,<1/3,5µS	30j$	Rhm	2SC4220
2SC4939	Si-NPN	=2SC4595:35W	30j$	Rhm	-
2SC494	Si-NPN	=2SC492:50V	23a$	Tos	BD245A,BDV91,2N4914..15,2SD985..
2SC4940	Si-NPN	Sw,Pow,1200/550V,4A,30W,<800/3300nS	15c	Shi	BU506F
2SC4941	Si-NPN	Sw,Pow,1500/800V,6A,65W,<500/3800nS	18c	Shi	BU508(A)F,2SC4303A,2SC4770,2SD2252..
2SC4942	Si-NPN	Sw,600/600V,1A,30MHz,<0,5/5,5µS	39b	Nec	-
2SC4942-AA1	Si-NPN	-	39	Nec	→2SC4942
2SC4942-AA2	Si-NPN	-	39	Nec	→2SC4942
2SC4942-AA3	Si-NPN	-	39	Nec	→2SC4942
2SC4943	Si-NPN	=2SC4572:Iso	17c	Sanyo	-
2SC4944	Si-NPN	=2SC4207:	45ba1(2mm)	Tos	-
2SC4944-GR	Si-NPN	-	45(2mm)	Tos	→2SC4944
2SC4944-Y	Si-NPN	-	45(2mm)	Tos	→2SC4944
2SC495	Si-NPN	AF,Sw-Pow,70V,1A,5W,100MHz	14h$	Tos	BD137,BD228,BD237,BD377,2SD794(A)...
2SC4953	Si-NPN	Sw,Pow,500/400V,3A,30W,<1/3,3µS	17c	Mat	2SC3570,2SC4052,2SC4160,2SC4533..
2SC4954	Si-NPN	UHF/SHF,9V,10mA,12GHz	35a	Nec	2SC5050
2SC4954-T82	Si-NPN	-	35	Nec	→2SC4954
2SC4955	Si-NPN	UHF/SHF,9V,30mA,12GHz	35a	Nec	2SC5050
2SC4955-T83	Si-NPN	-	35	Nec	→2SC4955
2SC4956	Si-NPN	=2SC4954:	44ze	Nec	2SC5078
2SC4956-T82	Si-NPN	-	44	Nec	→2SC4956
2SC4956-T83	Si-NPN	-	44	Nec	→2SC4956
2SC4957	Si-NPN	npn RF fT 12GHz @3V 10mA	-	Nec	-
2SC4958	Si-NPN	=2SC4954:	35a(2mm)	Nec	2SC5051
2SC4958-T82	Si-NPN	-	35(2mm)	Nec	→2SC4958
2SC4959	Si-NPN	=2SC4955:	35a(2mm)	Nec	2SC5051

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2SC4959-T83	Si-NPN	-	35(2mm)	Nec	→2SC4959
2SC496	Si-NPN	=2SC495:40V	14h$	Tos	BD135,BD226,BD375,2SD794(A)..
2SC4960	Si-NPN	Sw,Pow,900/800V,1A,40W,<1/4µS	16c	Mat	2SC4299,2SC4445
2SC4960A	Si-NPN	=2SC4960:900/900V	16c	-	2SC4426,2SC4583
2SC4961	Si-NPN	Sw,Pow,500/400V,5A,35W,<700/2300nS	17c	Mat	2SC3570,2SC4026,2SC4073,2SC4418..
2SC4962	Si-NPN+Diode	TV/Monitor-HD,1700V,6A,50W	?18c	Hit	2SC4766,2SD2253,BU2727DF
2SC4963	Si-NPN+Diode	TV/Monitor-HD,1700V,8A,50W	?18c	Hit	BU2727DF,BUH517D
2SC4964	Si-NPN	VHF/UHF,12V,0,1A,Ron=2Ω	35a	Hit	-
2SC4965	Si-NPN	-	35(2mm)	Hit	→2SC4965
2SC4966	Si-NPN	VHF/UHF,12V,0,1A,Ron=1,2Ω	35a	Hit	-
2SC4967	Si-NPN	-	35(2mm)	Hit	→2SC4967
2SC4968	Si-NPN	UHF-A,15V,80mA,0,6W,6GHz	7f	Mat	2SC3355,2SC3605
2SC4969	Si-NPN	=2SC3757:	35d	Mat	→2SC3757
2SC4969-Q	Si-NPN	-	?35	Mat	→2SC4969
2SC4969-R	Si-NPN	-	?35	Mat	→2SC4969
2SC497	Si-NPN	AF,Sw,100V,0,8A,0,6W,50MHz	2a$	Tos,Mic	BC141,BC300,BCX40,2N2102,2N2405..
2SC4971	Si-NPN	-	?35	Mat	→2SC4971
2SC4972	Si-NPN	=2SC2778:	35d	Mat	→2SC2778
2SC4972-B	Si-NPN	-	ч35	Mat	→2SC4972
2SC4972-C	Si-NPN	-	ч35	Mat	→2SC4972
2SC4973	Si-NPN	=2SC2404:	35d	Mat	→2SC2404
2SC4973-B	Si-NPN	-	?35	Mat	→2SC4973
2SC4973-C	Si-NPN	-	?35	Mat	→2SC4973
2SC4973-D	Si-NPN	-	?35	Mat	→2SC4973
2SC4974	Si-NPN	=2SC2480:	35d	Mat	→2SC2480
2SC4974-S	Si-NPN	-	?35	Mat	→2SC4974
2SC4974-T	Si-NPN	-	?35	Mat	→2SC4974
2SC4975	Si-NPN	-	?35	Mat	→2SC4975
2SC4976	Si-NPN	=2SC4564:12W	30j$	Sanyo	(→2SC4564)
2SC4977	Si-NPN	-	-	-	-
2SC4978	Si-NPN	Sw,Pow,Lo-sat,100V,3A,10W,50MHz	30j$	Shi	2SD1815..1816
2SC4979	Si-NPN	Sw,Pow,Lo-sat,100V,5A,10W,50MHz	30j$	Shi	2SC3303,2SC4332,2SC5103
2SC498	Si-NPN	=2SC497:80V	2a$	-	BC140..141,BC300..301,BCX40..
2SC4980	Si-NPN	Sw,Pow,Lo-sat,100V,5A,25W,50MHz	15c	Shi	2SC3540,2SC3691,2SC4549,2SC4596
2SC4981	Si-NPN	Sw,Pow,Lo-sat,100V,7A,25W,50MHz	15c	Shi	2SC3692,2SC4550
2SC4982	Si-NPN	Sw,Pow,Lo-sat,100V,10A,25W,50MHz	15c	Shi	2SC3693,2SC4551,2SC4595
2SC4983	Si-NPN	15V,1A,200MHz	35a	Sanyo	-
2SC4983-5	Si-NPN	-	35	Sanyo	→2SC4983
2SC4983-6	Si-NPN	-	35	Sanyo	→2SC4983
2SC4983-7	Si-NPN	-	35	Sanyo	→2SC4983
2SC4984	Si-NPN	15V,1,5A,200MHz	39b	Sanyo	2SC2983,2SC3443,2SC4377,2SD1621,..
2SC4984-S	Si-NPN	-	39	Sanyo	→2SC4984
2SC4984-T	Si-NPN	-	39	Sanyo	→2SC4984
2SC4984-U	Si-NPN	-	39	Sanyo	→2SC4984
2SC4985	Si-NPN	Sw,Pow,900/800V,1A,1,5W,<1/4µS	78b	Mat	(BUV9S)
2SC4986	Si-NPN	Sw,Pow,500/400V,2A,1,5W,<1/4µS	78b	Mat	(2SC3233,2SC3631)
2SC4987	Si-NPN	Sw,40V,0,2A,750MHz,8/18nS	35a(1,6mm)	Sanyo	-
2SC4987-B4	Si-NPN	-	35(1,6mm)	Sanyo	→2SC4987
2SC4987-B5	Si-NPN	-	35(1,6mm)	Sanyo	→2SC4987
2SC4987-B6	Si-NPN	-	35(1,6mm)	Sanyo	→2SC4987
2SC4988	Si-NPN	VHF/UHF,15V,0,1A,8,5GHz	39b	Hit	-
2SC4989	Si-NPN	UHF-Out,35V,18A,Pq>6SW(520MHz)	-	Mit	-
2SC499	Si-NPN	Nix,100V,0,02A,0,3W,150MHz	7c	Tos	BF422,BSW32,BSS38,BSX21..
2SC4990	Si-NPN	SMD	39b	Hit	-
2SC4991	Si-NPN	VHF/UHF,15V,50mA,9,5GHz	44ze	Hit	2SC4094,2SC4127,2SC4592
2SC4992	Si-NPN	-	44(2mm)	Hit	→2SC4992
2SC4993	Si-NPN	VHF/UHF,15V,20mA,10,5GHz	44ze	Hit	2SC4095,2SC5092,2SC5097
2SC4994	Si-NPN	-	44(2mm)	Hit	→2SC4994
2SC4995	Si-NPN	VHF/UHF,15V,50mA,11GHz	44ze(2mm)	Hit	-
2SC4997	Si-NPN	HF/Sw,Hi-beta,15V,0,1A,240MHz	35a(1,6mm)	Rhm	-
2SC4998	Si-NPN	-	35(2mm)	Rhm	→2SC4998
2SC50	Ge-NPN	HF/Sw,20V,0,2A,0,1W	1a	Mat	ASY28..29,ASY73..75
2SC500	Si-NPN	Vid,120V,0,02A,0,6W,175MHz	2a$	Tos	BF257..259,BF657..659,2N5058..59
2SC5000	Si-NPN	Sw,Pow,80V,10A,25W,90MHz	17c	Tos	2SC3693,2SC3748,2SC4551,(2SC3255)

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2SC5001(FS)	Si-NPN	AF-Pow,Lo-sat,30V,10A,10W,150MHz	30j$	Rhm	2SC4669
2SC5002	Si-NPN	Display-HD,1500/800V,7A,80W	18c	Sak	2SC3885A,2SC3895,2SC4757,BU4522AF
2SC5003	Si-NPN+Diode	=2SC5002:Int.Damper-Diode	18c	Sak	2SC3892A,2SC4762,2SC4916,BU4522DF
2SC5004	Si-NPN	UHF-Mix/Osc,20V,0,06A,3000MHz	-	Nec	-
2SC5004-FB	Si-NPN	UHF-Mix/Osc,20V,0,06A,3000MHz	35(1,6mm)	Nec	→2SC5004
2SC5005	Si-NPN	UHF-Mix/Osc,20V,0,03A,5500MHz	35a(1,6mm)	Nec	2SC4839,2SC5086
2SC5005-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5005
2SC5006	Si-NPN	UHF,20V,0,1A,4500MHz	35a(1,6mm)	Nec	-
2SC5007	Si-NPN	UHF,20V,0,065A,7000MHz	35a(1,6mm)	Nec	2SC4839,2SC5086
2SC5007-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5007
2SC5008	Si-NPN	UHF,20V,0,035A,8000MHz	35a(1,6mm)	Nec	2SC4840,2SC5066,2SC5091
2SC5008-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5008
2SC5009	Si-NPN	UHF/SHF,9V,10mA,12GHz	35a(1,6mm)	Nec	2SC5246
2SC5009-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5009
2SC501	Si-NPN	GenP,60V,0,3A,0,75W,200MHz	2a$	Tos	BC140..141,BC300..302,2N3053..
2SC5010	Si-NPN	UHF/SHF,9V,30mA,12GHz	35a(1,6mm)	Nec	2SC5139,2SC5247
2SC5010-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5010
2SC5011-EB	Si-NPN	-	44(2mm)	Nec	→2SC5011
2SC5011-FB	Si-NPN	-	44(2mm)	Nec	→2SC5011
2SC5011-GB	Si-NPN	-	44(2mm)	Nec	→2SC5011
2SC5011-Q	Si-NPN	UHF,20V,0,1A,6,5GHz,B=50-100	-	Nec	-
2SC5011-R	Si-NPN	UHF,20V,0,1A,6,5GHz,B=80-160	-	Nec	-
2SC5011-S	Si-NPN	UHF,20V,0,1A,6,5GHz,B=25-250	-	Nec	-
2SC5012-EB	Si-NPN	-	44(2mm)	Nec	→2SC5012
2SC5012-FB	Si-NPN	-	44(2mm)	Nec	→2SC5012
2SC5012-GB	Si-NPN	-	44(2mm)	Nec	→2SC5012
2SC5012-Q	Si-NPN	UHF,20V,65mA,9GHzB=50-100	44ze(2mm)	Nec	-
2SC5012-R	Si-NPN	UHF,20V,65mA,9GHz,B=80-160	44ze(2mm)	Nec	-
2SC5012-S	Si-NPN	UHF,20V,65mA,9GHzB=125-250	44ze(2mm)	Nec	-
2SC5013	Si-NPN	UHF,20V,35mA,10GHz	44ze(2mm)	Nec	2SC4843,2SC5093
2SC5013-EB	Si-NPN	-	44(2mm)	Nec	→2SC5013
2SC5013-FB	Si-NPN	-	44(2mm)	Nec	→2SC5013
2SC5013-GB	Si-NPN	-	44(2mm)	Nec	→2SC5013
2SC5013-Q	Si-NPN	npnfT10GHz	-	Nec	-
2SC5013-R	Si-NPN	npnfT10GHz	-	Nec	-
2SC5013-S	Si-NPN	npnfT10GHz	-	Nec	-
2SC5014	Si-NPN	UHF,9V,10mA,12GHz	44ze(2mm)	Nec	2SC5079
2SC5014-KB	Si-NPN	-	44(2mm)	Nec	→2SC5014
2SC5015	Si-NPN	UHF,9V,30mA,12GHz	44ze(2mm)	Nec	-
2SC5015-KB	Si-NPN	-	44(2mm)	Nec	→2SC5015
2SC5016	Si-NPN	VHF-Mix,15V,0,05A,1300MHz	35d	Mat	BF599,BFS20,2SC3015,2SC3374
2SC5018	Si-NPN	Sw,500/400V,0,8A,1W,20MHz	9c	Mat	-
2SC5019	Si-NPN	UHF-A,15V,80mA,6GHz	39b	Mat	BFQ193,2SC3301,2SC3357,2SC3607
2SC502	Si-NPN	HF-Dr/Out,60V,1A,0,8W,>150MHz	2a$	Tos	BFS22,BFS51,BFQ42,2N4427..
2SC5020	Si-NPN	AM/FM/TV-IF,30V,15mA,650MHz	35a(2mm)	Matsushita	2SC3931
2SC5020-P	Si-NPN	-	35(2mm)	Mat	→2SC5020
2SC5020-Q	Si-NPN	-	35(2mm)	Mat	→2SC5020
2SC5020-R	Si-NPN	-	35(2mm)	Mat	→2SC5020
2SC5021	Si-NPN	=2SC5020:	35a(1,6mm)	Mat	2SC4627,2SC4655,2SC4915
2SC5022	Si-NPN	Sw,Pow,1500/1500V,20mA,B>10	17c	Hit	2SC4633,2SC4635
2SC5023	Si-NPN	=2SC4708:Iso,8W,1GHz	14b	Hit	2SC3953,(2SC3598..99)
2SC5024	Si-NPN	=2SC4704:Iso,8W	14b	Hit	2SC3956,(2SC3601,2SC4704)
2SC5025	Si-NPN	=2SC3652:Iso	14b	Hit	-
2SC5026	Si-NPN	Lo-sat,80V,1A,120MHz	39b	Mat	2SC4409,2SD1615A
2SC5026-R	Si-NPN	-	39	Mat	→2SC5026
2SC5026-S	Si-NPN	-	39	Mat	→2SC5026
2SC5027	Si-NPN	Sw,CTV-HD-Dr,300/300V,0,1A,70MHz	12b	Tos	2SC3271,2SC3789..90,2SC4828
2SC5028	Si-NPN	GenP,Lo-sat,60V,2A,1,3W,100MHz	12b	Tos	(2SD1682)
2SC5029	Si-NPN	GenP,50V,3A,1,3W,100MHz	12b	Tos	(2SC3420)
2SC503(D,M)	Si-NPN	GenP,100V,0,6A,0,8W,80MHz	2a$	Tos,Mic	BC141,BC300,BCX40,BSW39..
2SC5030	Si-NPN	Hi-beta,Lo-sat,50V,5A,1,3W,150MHz	12b	Tos	-
2SC5032	Si-NPN	Sw,Pow,500/400V,3A,30W,<1/3,3µS	17c	Mat	2SC4052,2SC4160,2SC4421,2SC4533..
2SC5034	Si-NPN	Sw,Pow,500/400V,7A,35W,<1/2,3µS	17c	Mat	BU306F,2SC3571,2SC4130,2SC4559..
2SC5035	Si-NPN	Sw,Pow,800/500V,5A,40W,<1,5/4µS	17c	Mat	BUT11(A)F,2SC3353,2SC3750,2SC3795(A)

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2SC5036	Si-NPN	Sw,Pow,900/800V,1A,30W,<700/2800nS	17c	Mat	BUX85F,2SC3794A,2SC3978(A)
2SC5036A	Si-NPN	=2SC5036:1000/800V	17c	-	BUX85F,2SC3751,2SC3978(A),2SC4231
2SC5037	Si-NPN	Sw,Pow,900/800V,3A,40W,<700/2800nS	17c	Mat	2SC3752,2SC3979(A),2SC4304,2SC4517(A)
2SC5037A	Si-NPN	=2SC5037:1000/800V	17c	-	2SC3752,2SC3979A,2SC4234,2SC4517A
2SC5039	Si-NPN	Hi-beta,Lo-sat,30V,2A,0,9W,B>1200	7c(9mm)	Tos	2SC3225,2SC4389
2SC504	Si-NPN	=2SC503:80V	2a$	Tos,Mic	2N5339,BC140..141,BC300..301,BSW39..
2SC5041	Si-NPN+Diode	=2SC5042:Int.Damper-Diode	18c	Sanyo	BUH517D,2SC4963
2SC5042	Si-NPN	CRT HD,Hi-res,1600/800V,7A,60W	18c	Sanyo	BUH417,BUH517,2SC4797
2SC5043	Si-NPN+Diode	=2SC5044:Int.Damper-Diode	18c	Sanyo	2SC5143D,BU2727DX
2SC5044	Si-NPN	CRT HD,Hi-res,1600/800V,10A,70W	18c	Sanyo	BU2727AF,2SC4879
2SC5045	Si-NPN	CRT HD,Hi-res,1600/800V,15A,75W	18c	Sanyo	2SC5478,BU4730AL
2SC5046	Si-NPN	CRT HD,Hi-res,1600/800V,15A,180W	77j$	Sanyo	2SC5057,2SC5144,BU4730AL
2SC5047	Si-NPN	CRT HD,Hi-res,1600/800V,25A,250W	77j$	Sanyo	-
2SC5048	Si-NPN	Display HD,Hi-res,1500/600V,12A,50W	18c	Tos	BU2525AF,BU2527AF,BU4523AX
2SC5049	Si-NPN	VHF/UHF,15V,20mA,10GHz	35a	Hitachi	BFR505,2SC3585,2SC5094
2SC505	Si-NPN	Vid,300/300V,0,2A,0,6W,60MHz	2a$	Tos,Mic	BF259,BF659,BFR59,BFS89,2N5058
2SC5050	Si-NPN	VHF/UHF,15V,50mA,11GHz	35a	Hitachi	-
2SC5051	Si-NPN	-	35(2mm)	Hit	→2SC5051
2SC5052	Si-NPN	GenP,120V,0,8A,1W,120MHz	9c	Tos	2SC2235,2SC2383,2SC3332,2SC4612..
2SC5053	Si-NPN	Lo-sat,60V,1A,150MHz	39b	Rhm	2SC3444,2SD1615,2SD1622..23
2SC5053-P	Si-NPN	-	39	Rhm	→2SC5053
2SC5053-Q	Si-NPN	-	39	Rhm	→2SC5053
2SC5053-R	Si-NPN	-	39	Rhm	→2SC5053
2SC5057	Si-NPN	TV/Monitor-HD,1700/900V,20A,200W	77j$	Hit	-
2SC5058	Si-NPN	TV/Monitor-HD,1700/900V,12A,150W	77j$	Hit	2SC4880,2SC4896,BU4730AL
2SC506	Si-NPN	=2SC505:200/200V	2a$	Tos,Mic	BF258..259,BFR58..59,2N5058..59
2SC5060	Si-N-Darl+Di	+Z-Di(B→C),90V,1A,1W,80MHz,B>1000	9c	Rhm	-
2SC5061	Si-NPN	AF-Driver,-/80V,0,7A,0,9W	7c(9mm)	Rhm	2SC2383,2SC3228,2SD1292,2SD1812
2SC5062	Si-NPN	Lo-sat,-/20V,3A,0,9W	7c(9mm)	Rhm	2SC4781,2SD1347
2SC5063	Si-NPN	Sw,Pow,500/400V,1,5A,25W,<700/2300nS	30j$	Mat	2SC3403,2SC4754
2SC5064	Si-NPN	VHF/UHF,20V,30mA,7GHz	35a	Toshiba	BFQ67,BFR182..183,2SC3585
2SC5064-O	Si-NPN	-	35	Tos	→2SC5064
2SC5064-Y	Si-NPN	-	35	Tos	→2SC5064
2SC5065	Si-NPN	=2SC5064:	35a(2mm)	Tos	BFQ67W,BFR182W..183W,2SC5190
2SC5065-O	Si-NPN	-	35(2mm)	Tos	→2SC5065
2SC5065-Y	Si-NPN	-	35(2mm)	Tos	→2SC5065
2SC5066	Si-N	=2SC5064:	35a(1,6mm)	Tos	2SC4840,2SC5108
2SC5066F	Si-N	=2SC5064:	flat	Tos	2SC4840,2SC5108
2SC5066-O	Si-NPN	-	35(1,6mm)	Tos	→2SC5066
2SC5066-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC5066
2SC5067	Si-NPN	TV/Monitor-HD,1500/800V,8A,50W	?18c	Hit	BU2508AF,BU4522AF,2SC3896A,2SC4757,2SD2372,..
2SC5068	Si-NPN	TV/Monitor-HD,1500/800V,10A,50W	?18c	Hit	BU2520AF,2SC4199A,2SC4542,2SC4759
2SC5068A	Si-NPN	=2SC5068:12A	?18c	-	BU2525AF,2SC4692,2SC5105
2SC5069	Si-NPN	=2SC3807:SMD	39b	Sanyo	-
2SC507	Si-NPN	Nix,Vid,170V,0,1A,0,75W,250MHz	2a$	Tos,Mic	BF257..259,BF657..659,2N5058..59
2SC5070	Si-NPN	=2SC5069:	?12b	Sanyo	-
2SC5071	Si-NPN	Sw,Pow,500/400V,12A,100W,10MHz	18c	Sak	2SC4297,2SC4423,(BUW13(A),BUV48..)
2SC5072	Si-NPN	=2SC4911K:	35a(1,6mm)	Rhm	2SC4987
2SC5073	Si-NPN	=2SC4699K:	35a(1,6mm)	Rhm	2SC4987
2SC5075	Si-NPN	Sw-Reg,500/400V,2A,1,3W,<1/3,5µS	12b	Tos	(2SC4917)
2SC5076	Si-NPN	GenP,Lo-sat,60V,5A,1,3W,120MHz	12b	Tos	(2SD1903)
2SC5077	Si-NPN	Sw,Pow,800/500V,7A,45W,<1/3,3µS	17c	Mat	BU307F,BUT12AF,BUT22BF,CF
2SC5077A	Si-NPN	=2SC5077:900/500V	17c	-	BUF405FI,BUT12AF,BUTCF
2SC5078	Si-NPN	VHF/UHF,15V,20mA,12GHz	44ze	Hit	-
2SC5079	Si-NPN	-	44(2mm)	Hit	→2SC5079
2SC508	Si-NPN	TV-HD,180/60V,4A,20W,25MHz	22a$	Tos	BU406..408,2SD823,2SD1136,2SD1159,..
2SC5080	Si-NPN	VHF/UHF,15V,50mA,13,5GHz	44ze	Hit	-
2SC5081	Si-NPN	-	44(2mm)	Hit	→2SC5081
2SC5082M	Si-NPN	TV-IF,-/25V,50mA,650MHz	9c	Rhm	BF920,BF921S,BF959
2SC5083	Si-NPN	=2SC5082M:PinS 14mm	9c	Rhm	→2SC5082M
2SC5084	Si-NPN	VHF/UHF,20V,80mA,7GHz	35a	Toshiba	BFR193,BFR520,2SC3356,2SC3445
2SC5084-O	Si-NPN	-	35	Tos	→2SC5084
2SC5084-Y	Si-NPN	-	35	Tos	→2SC5084
2SC508S	Si-NPN	=2SC5084:	35a(2mm)	Tos	BFS520,BFS540

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2SC5085-O	Si-NPN	-	35(2mm)	Tos	→2SC5085
2SC5085-Y	Si-NPN	-	35(2mm)	Tos	→2SC5085
2SC5086	Si-N	=2SC5084:	35a(1,6mm)	Tos	-
2SC5086F	Si-N	=2SC5084:	flat	Tos	-
2SC5086-O	Si-NPN	-	35(1,6mm)	Tos	→2SC5086
2SC5086-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC5086
2SC5087	Si-NPN	VHF/UHF,20V,80mA,7GHz	44ze	Tos	-
2SC5087-O	Si-NPN	-	44	Tos	→2SC5087
2SC5087-Y	Si-NPN	-	44	Tos	→2SC5087
2SC5088	Si-NPN	=2SC5087:	44ze(2mm)	Tos	-
2SC5088-O	Si-NPN	-	44(2mm)	Tos	→2SC5088
2SC5088-Y	Si-NPN	-	44(2mm)	Tos	→2SC5088
2SC5089	Si-NPN	VHF/UHF,20V,40mA,10GHz	35a	Toshiba	2SC3583,2SC3585,2SC3904,2SC4591
2SC5089-O	Si-NPN	-	35	Tos	→2SC5089
2SC5089-R	Si-NPN	-	35	Tos	→2SC5089
2SC509(G)	Si-NPN	GenP,35V,0,5A,0,6W,100MHz	9b	Toshiba	BC337,BC635,BC637,2SC3377..
2SC5090	Si-NPN	=2SC5089:	35a(2mm)	Tos	2SC4593,2SC5190
2SC5090-O	Si-NPN	-	35(2mm)	Tos	→2SC5090
2SC5090-R	Si-NPN	-	35(2mm)	Tos	→2SC5090
2SC5091	Si-N	=2SC5089:	35a(1,6mm)	Tos	-
2SC5091F	Si-N	=2SC5089:	flat	Tos	-
2SC5091-O	Si-NPN	-	35(1,6mm)	Tos	→2SC5091
2SC5091-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC5091
2SC5092	Si-NPN	VHF/UHF,20V,40mA,10GHz	44ze	Tos	2SC4094..95,2SC4127
2SC5092-O	Si-NPN	-	44	Tos	→2SC5092
2SC5092-R	Si-NPN	-	44	Tos	→2SC5092
2SC5093	Si-NPN	=2SC5092:	44ze(2mm)	Tos	2SC4843
2SC5093-O	Si-NPN	-	44(2mm)	Tos	→2SC5093
2SC5093-R	Si-NPN	-	44(2mm)	Tos	→2SC5093
2SC5094	Si-NPN	VHF/UHF,20V,15mA,10GHz	35a	Toshiba	BFR505,2SC3585,2SC5089
2SC5094-O	Si-NPN	-	35	Tos	→2SC5094
2SC5094-R	Si-NPN	-	35	Tos	→2SC5094
2SC5095	Si-NPN	=2SC5094:	35a(2mm)	Tos	BFS505,2SC5090,2SC5190
2SC5095-O	Si-NPN	-	35(2mm)	Tos	→2SC5095
2SC5095-R	Si-NPN	-	35(2mm)	Tos	→2SC5095
2SC5096	Si-N	=2SC5094:	35a(1,6mm)	Tos	2SC4840..41,2SC5091
2SC5096F	Si-N	=2SC5094:	flat	Tos	2SC4840..41,2SC5091
2SC5096-O	Si-NPN	-	35(1,6mm)	Tos	→2SC5096
2SC5096-R	Si-NPN	-	35(1,6mm)	Tos	→2SC5096
2SC5097	Si-NPN	VHF/UHF,20V,15mA,10GHz	44ze	Tos	2SC4095,2SC5092
2SC5097-O	Si-NPN	-	44	Tos	→2SC5097
2SC5097-R	Si-NPN	-	44	Tos	→2SC5097
2SC5098	Si-NPN	=2SC5097:	44ze(2mm)	Tos	2SC4843,2SC5093
2SC5098-O	Si-NPN	-	44(2mm)	Tos	→2SC5098
2SC5098-R	Si-NPN	-	44(2mm)	Tos	→2SC5098
2SC5099	Si-NPN	AF,Sw-Pow,120V,6A,60W,20MHz	18c	Sak	2SC4385,2SC4689,2SD2064,(BD245C..F)
2SC509GTM	Si-NPN	=2SC509:0,8W	7c	-	BC337,BC635,BC637,2SC3377..
2SC51	Si-NPN	HF-Dr/Out,60V,0,3A,1W,180MHz	2a$	Fui	BFX55,2N2218..19,2N3299..3300..
2SC510(M)	Si-NPN	HF/AF,Sw,140/100V,1,5A,0,8W,60MHz	2a$	Tos	BSS43,BSW68,2SC1860
2SC5100	Si-NPN	AF,Sw-Pow,160V,8A,75W,20MHz	18c	Sak	2SC4386,(BD245D..F)
2SC5101	Si-NPN	AF,Sw-Pow,200V,10A,80W,20MHz	18c	Sak	2SC4387,(BD245F)
2SC5103	Si-NPN	Sw,Pow,Lo-sat,100V,5A,10W,120MHz	30j$	Rhm	2SC3303
2SC5104	Si-NPN	Sw,Pow,500/400V,3A,30W,<1/3,3µS	31J$	Mat	2SC4219,2SC4597,(BUT11(A)F)
2SC5105	Si-NPN	Monitor-HD,1500/800V,12A,50W	?18c	Hit	BU2525AF,BU4530AL,2SC4692
2SC5106	Si-NPN	VHF/UHF,20V,30mA,6GHz	35a	Toshiba	BFR182,2SC3011,2SC5064
2SC5106-O	Si-NPN	-	35	Tos	→2SC5106
2SC5106-Y	Si-NPN	-	35	Tos	→2SC5106
2SC5107	Si-NPN	=2SC5106:	35a(2mm)	Tos	BFR182W,2SC5065
2SC5107-O	Si-NPN	-	35(2mm)	Tos	→2SC5107
2SC5107-Y	Si-NPN	-	35(2mm)	Tos	→2SC5107
2SC5108	Si-N	=2SC5106:	35a(1,6mm)	Tos	2SC5066
2SC5108F	Si-N	=2SC5106:	flat	Tos	2SC5066
2SC5108-O	Si-NPN	-	35(1,6mm)	Tos	→2SC5108
2SC5108-Y	Si-NPN	-	35(1,6mm)	Tos	→2SC5108

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2SC5109	Si-NPN	VHF/UHF,20V,60mA,5GHz	35a	Toshiba	BF770,BFQ67,BFR183,2SC3513,2SC3704
2SC5109-O	Si-NPN	-	3S	Tos	→2SC5109
2SC5109-Y	Si-NPN	-	3S	Tos	→2SC5109
2SC511	Si-NPN	=2SC510:120/80V	2a$	Tos	BSS42..43,BSW67..68,BSX47,BSV84..
2SC5110	Si-NPN	=2SC5109:	35a(2mm)	Tos	BFQ67W,BFR183W,2SC3937
2SC5110-O	Si-NPN	-	35(2mm)	Tos	→2SC5110
2SC5110-Y	Si-NPN	-	35(2mm)	Tos	→2SC5110
2SC5111	Si-N	=2SC5109:	35a(1,6mm)	Tos	2SC5086
2SC5111F	Si-N	=2SC5109:	flat	Tos	2SC5086
2SC5111-O	Si-NPN	-	3S(1,6mm)	Tos	→2SC5111
2SC5111-Y	Si-NPN	-	3S(1,6mm)	Tos	→2SC5111
2SC5112	Si-NPN	Sw,Pow,-/500,5A,40W	17j$	Rhm	BUT11,BUT18,BUV46,2SC3047..
2SC5113	Si-NPN	Sw,Pow,750/450V,5A,35W,<0,5/1,4Sµs	17c	Rhm	BUT11F,BUT18F,BUV46FI,2SC3750..
2SC5114	Si-NPN	Sw,Pow,-/500,5A,80W	16c	Rhm	BUW11F,2SC4300,2SC4427,2SC4457..
2SC5115	Si-NPN	Sw,Pow,-/500,5A,35W	30j$	Rhm	2SC4172,2SC4222,2SC4600,(BUT11,..)
2SC5116	Si-NPN	Sw,Pow,-/550,4A,40W	17j$	Rhm	BUT11,BUT18,BUV46,2SC3491..
2SC5117	Si-NPN	=2SC5116:Iso,35W	17c	Rhm	BUT11F,BUT18F,BUV46FI,2SC3750..
2SC5118	Si-NPN	=2SC5116:Iso,80W	16c	Rhm	BUW11F,2SC4300,2SC4427,2SC4457..
2SC5119	Si-NPN	Sw,Pow,-/550,4A,35W	30j$	Rhm	2SC4172,2SC4222,2SC4600,(BUT11,..)
2SC512(M)	Si-NPN	=2SC510:100/60V	2a$	Tos	BCX40,BSW67..68,BSX46..47..
2SC5120	Si-NPN	Vid-Out,150/150V,0,2A,8W,500MHz	14b	Hit	2SC3787,2SC3956
2SC5121	Si-NPN	Vid,400/400V,0,07A,>50MHz	14b	Mat	(BF850,2SC3418)
2SC5122	Si-NPN	Sw-Reg,400/400V,0,05A,0,9W	7c(9mm)	Tos	2SC2267,2SC3469,2SC4166,2SD1385
2SC5124	Si-NPN	HD,1500/800V,10A,100W	18c	Sak	BU2520AF,2SC4589,2SC4759,2SD2373..
2SC5125	Si-NPN	VHF-Out,35V,25A,Pq>80W(175MHz)	-	Mit	-
2SC5127	Si-NPN	Sw,Pow,800/500V,1,5A,25W,<1/3,3µS	17c	Mat	BUX84F..85F,2SC3352,2SC3794(A)..
2SC5127A	Si-NPN	=2SC5127:900/500V	17c	-	BUX85F,2SC3794(A),2SC3978(A)
2SC5128	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/3,3µS	17c	Mat	BUT11(A)F,2SC3353,2SC3750,2SC3795,..
2SC5129	Si-NPN	Display-HD,Hi-res,1500/600V,10A,50W,sat<3V(6A)	18c	Tos	BU2520AF,BUH715,2SC4542
2SC513	Si-NPN	=2SC510:70/40V	2a$	Tos	BCX40,BSW65..68,BSX45..47..
2SC5130	Si-NPN	Sw-Reg,600/400V,5A,30W,20MHz	17c	Sak	BUT11(A)F,2SC3750,2SC3795,2SC4054,..
2SC5132	Si-NPN+Diode	=2SC5133:Iso	?18c	Hit	2SC4764,2SC4122,2SC4294,2SD2370
2SC5132A	Si-NPN+Diode	=2SC5133:Iso,8A	?18c	-	BU2508DF,BU4508DF,2SC4124,2SC4763,2SD2371
2SC5133	Si-NPN+Diode	Monitor-HD,1500V,6A,50W	18j$	Hit	BU2508D,BU4515DX,2SC3482,2SC4122,2SC4292
2SC5136	Si-NPN	VHF/UHF,25V,50mA,3,8GHz	35a(1,6mm)	Hitachi	2SC5111,2SC5141
2SC5137	Si-NPN	VHF/UHF,15V,20mA,10GHz	35a(1,6mm)	Hitachi	2SC4841,2SC5096
2SC5138	Si-NPN	VHF/UHF,20V,30mA,6GHz	35a(1,6mm)	Hitachi	2SC5066,2SC5108
2SC5139	Si-NPN	VHF/UHF,15V,50mA,11GHz	35a(1,6mm)	Hit	2SC5247
2SC514	Si-NPN	AF,Sw-Vid-Pow,300/300V,0,1A,4W,20MHz	?22$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC5140	Si-NPN	VHF/UHF,15V,20mA,9GHz	35a(1,6mm)	Hitachi	2SC4841,2SC5096
2SC5141	Si-NPN	VHF/UHF,20V,50mA,5,8GHz	35a(1,6mm)	Hitachi	-
2SC5142	Si-NPN	Display-HD,1500/600V,20A,200W	77j$	Tos	2SC3994,2SC4290(A),2SC4897BU4550AL,
2SC5143	Si-NPN+Diode	Display-HD,Hi-res,1700/700V,10A,50W	18c	Tos	BU2727DX
2SC5144	Si-NPN	Display-HD,Hi-res,1700/600V,20A,200W	77j$	Tos	2SC5057
2SC5145	Si-NPN	Sw,Pow,800/500V,5A,40W,<1/4µS	30j$	Mat	2SC4172,2SC4222,2SC4600,(BUT11(A)..)
2SC5147	Si-NPN	Vid,300/300V,0,1A,10W,100MHz	17c	Rhm	2SC3565,2SC3942,2SC3945,2SC4075
2SC5148	Si-NPN	Display-HD,Hi-res,1500/600V,8A,50W	18c	Tos	BU2525AF,BU4508AX,2SC3896,2SC4758
2SC5149	Si-NPN+Diode	=2SC5148:Int.Damper-Diode	18c	Tos	BU2520DF,2SC3893A,2SC4763
2SC515(A)	Si-NPN	AF,Sw-Vid-Pow,300/300V,0,1(A=0,15)A,6W	22a$	Tos	2SC1505..1507,2SC1755..1757,2SC1905
2SC5150	Si-NPN	Display-HD,Hi-res,1700/700V,10A,50W	18c	Tos	BU2722AF,BU2727AF
2SC5154	Si-NPN	GenP,160/160V,1,5A,1,3W,100MHz	12b	Tos	(2SC3117,2SD669,2SD1563A)
2SC5155	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,50V,3A,20W,260MHz,B=800..3200,140/1620nS	30j$	Sanyo	(2SD1584)
2SC5156	Si-NPN	Sw,Pow,1000/800V,3A,70W,4MHz,<1/3µS	18c	Mat	BUW11AF,2SC4426,2SC4583
2SC5157	Si-NPN	Sw,Pow,1000/800V,5A	18c	Mat	BUW11AF,2SC4427,2SC4882
2SC5158	Si-NPN	Sw,Pow,500/400V,10A,70W,<700/2300nS	18c	Mat	2SC4296,(BUV47(A..C),BUW12(A),..)
2SC5159	Si-NPN	Sw,Pow,900/800V,3A,70W,<700/2800nS	18c	Mat	BUW11AF,2SC4299,2SC4445
2SC516	Si-NPN	GenP,100/80V,1,5A,0,8W,50MHz	2a$	Tos	BCX40,BSW66..68,BSX46..47..
2SC5160	Si-NPN	Sw,Pow,500/400V,7A,70W,<700/2300nS	18c	Mat	2SC4296,(BUP22(A..C),BUW12(A),..)
2SC5161(FS)	Si-NPN	Sw,Pow,400/400V,2A,10W	30j$	Rhm	2SC4616
2SC5162(FS)	Si-NPN	Sw,Pow,-/600V,1A,10W	30j$	Rhm	2SC3363
2SC5163	Si-NPN	TV/Monitor-HD,1500V,7A,tf<500nS	18c	Mat	2SC3885A,2SC3895,2SC4757,2SC5042..
2SC5164	Si-NPN	TV/Monitor-HD,1500/700V,10A,60W	18c	Mat	BU2520AF,2SC4542,2SC4759,2SC5129..
2SC5165	Si-NPN	TV/Monitor-HD,1500V,20A,tf<500nS	18c	Mat	-
2SC5166	Si-NPN	TV/Monitor-HD,1500V,10A,tf<800nS	18c	Mat	BU2520AF,2SC4542,2SC4759,2SC5129..

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2SC5167	Si-NPN	TV/Monitor-HD,1500V,20A,tf<800nS	18c	Mat	-
2SC5168	Si-NPN	Dual,50V,0,1A,0,2W,150MHz	5-SIP	Mit	-
2SC5169	Si-NPN	Dual,100V,0,05A,0,2W,150MHz	5-SIP	Mit	-
2SC516A	Si-NPN	=2SC516:140/100V	2a$	Tos	BSS43,BSW68,2SC1860
2SC517	Si-NPN	HF/Sw-Pow,60V,2A,Pq>4W(50MHz)	43a$	Tos	-
2SC5170	Si-NPN	Dual,100V,0,1A,0,2W,100MHz	5-SIP	Mit	-
2SC5171	Si-NPN	TV,Pow,180/180V,2A,20W,200MHz	17c	Tos	2SC3298A,2SC4159,2SC4883A
2SC5172	Si-NPN	Sw-Reg,600/400V,5A,25W,<700/3000nS	17c	Tos	BUT11(A)F,2SC3750,2SC3795,2SC4054,..
2SC5173	Si-NPN	Vid,Sw,Pow,300/300V,0,1A,70MHz	15c	Tos	2SC3565,2SC3942,2SC3945,2SC4075
2SC5174	Si-NPN	GenP,230/230V,1A,1,8W,100MHz	15c	Tos	2SC4793
2SC5175	Si-NPN	GenP,Lo-sat,60V,5A,1,8W,100MHz	15c	Tos	2SC3540,2SC3746..47,2SC3691
2SC5176	Si-NPN	GenP,Lo-sat,100V,5A,1,8W,120MHz	15c	Tos	2SC3540,2SC3691,2SC4549,2SC4596
2SC5177	Si-NPN	SHF,5V,10mA,13GHz	35a	Nec	-
2SC5177-FB	Si-NPN	-	35	Nec	→2SC5177
2SC5178(R)	Si-NPN	SHF,5V,10mA,13,5GHz	44ze	Nec	2SC5078
2SC5178-FB	Si-NPN	-	44	Nec	→2SC5178
2SC5179	Si-NPN	SHF,5V,10mA,13GHz	35a(2mm)	Nec	-
2SC5179-FB	Si-NPN	-	35(2mm)	Nec	→2SC5179
2SC518	Si-NPN	TV-HD,140V,5A,50W	23a$	Toshiba	BDW51C,BU104,BU606..608,2SD916,2SD1154
2SC5180	Si-NPN	SHF,5V,10mA,15,5GHz	44ze(2mm)	Nec	2SC5079
2SC5180-FB	Si-NPN	-	44(2mm)	Nec	→2SC5180
2SC5181	Si-NPN	SHF,5V,10mA,13GHz	35a(1,6mm)	Nec	2SC5246
2SC5181-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5181
2SC5182	Si-NPN	SHF,5V,30mA,12GHz	35a	Nec	2SC5050
2SC5182-FB	Si-NPN	-	35	Nec	→2SC5182
2SC5183	Si-NPN	npn RF fT 12GHz@2V 20mA	-	Nec	-
2SC5183(R)	Si-NPN	SHF,5V,30mA,12,5GHz	44ze	Nec	2SC5080
2SC5183-FB	Si-NPN	-	44	Nec	→2SC5183
2SC5184	Si-NPN	SHF,5V,30mA,11GHz	35a(2mm)	Nec	2SC5051
2SC5184-FB	Si-NPN	-	35(2mm)	Nec	→2SC5184
2SC5185	Si-NPN	SHF,5V,30mA,13GHz	44ze(2mm)	Nec	2SC5081
2SC5185-FB	Si-NPN	-	44(2mm)	Nec	→2SC5185
2SC5186	Si-NPN	SHF,5V,30mA,11GHz	35a(1,6mm)	Nec	2SC5139,2SC5247
2SC5186-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5186
2SC5187	Si-NPN	Sw,25V,1,5A,50/180nS	39b	Sanyo	2SC2982,2SC4377,2SD1621,2SD1766,..
2SC5188	Si-NPN	Sw,25V,3A,50/120nS	39b	Sanyo	2SD1119,2SD1620,2SD2150
2SC5189	Si-NPN	Sw,25V,5A,50/180nS	39b	Sanyo	2SD1963,2SD2540
2SC518A	Si-NPN	=2SC518:180V	23a$	-	BDW51C,BU104,BU606..608,2SD916,2SD1154
2SC519	Si-NPN	AF,Sw-Pow,110/100V,7A,50W,10MHz	23a$	Tos	BD245C,BD550,2N4348,2SD1046..
2SC5190	Si-NPN	SHF/UHF-A,9V,30mA,10GHz	35a(2mm)	Mat	2SC4593,2SC4805
2SC5191	Si-NPN	UHF,9V,0,1A,4500MHz	35a	Nec	BFR106,2SC3356
2SC5191-FB	Si-NPN	-	35	Nec	→2SC5191
2SC5192(R)	Si-NPN	UHF,9V,0,1A,4500MHz	44ze	Nec	-
2SC5192-FB	Si-NPN	-	44	Nec	→2SC5192
2SC5193	Si-NPN	UHF,9V,0,1A,4500MHz	35a(2mm)	Nec	-
2SC5193-FB	Si-NPN	-	35(2mm)	Nec	→2SC5193
2SC5194	Si-NPN	UHF,9V,0,1A,5000MHz	44ze(2mm)	Nec	2SC5011
2SC5194-FB	Si-NPN	-	44(2mm)	Nec	→2SC5194
2SC5195	Si-NPN	UHF,9V,0,1A,5000MHz	35a(1,6mm)	Nec	2SC5006
2SC5195-FB	Si-NPN	-	35(1,6mm)	Nec	→2SC5195
2SC5196	Si-NPN	AF-Out,80/80V,6A,60W,30MHz	18j$	Tos	BD245C,BDV93,2SC3256,2SD895..
2SC5197	Si-NPN	AF-Out,120/120V,8A,80W,30MHz	18j$	Tos	BD245C,BD545D,2SC3181,2SD718..
2SC5198	Si-NPN	AF-Out,140/140V,10A,100W,30MHz	18j$	Tos	BD245D,2SC2837,2SC2706,2SC3182..
2SC5199	Si-NPN	AF-Out,180/180V,12A,120W,30MHz	77j$	Tos	2SC3281,2SD1975,2SD2155
2SC519A(A-M)	Si-NPN	=2SC519:130/110V,0,4/4,9µS	23a$	-	BD245D,2N4348,2SC2706,2SD1046..
2SC52	Si-NPN	HF-Dr,40V,0,1A,0,5W,350MHz	2a$	Fui	BFW16..17,BFX55
2SC520(A,A-M)	Si-NPN	=2SC519..:100/80V	23a$	Tos	BD245C,BDV95,BDX95,2SD718..
2SC5200	Si-NPN	AF-Out,230/230V,15A,150W,30MHz	77j$	Tos	2SC4029
2SC5201	Si-NPN	Sw,600/600V,0,05A,0,9W,30MHz	7c(9mm)	Tos	2SD1573
2SC5206	Si-NPN	Sw,Pow,500/400V,5A,25W,tf=600nS	17c	Hit	2SC3570,2SC4026,2SC4073,2SC4418..
2SC5207A	Si-NPN	Display-HD,1500/800V,10A,50W	?18c	Hit	BU2520AF,BUH715,2SC5129
2SC5208	Si-NPN	Sw,600/400V,0,8A,1,3W,<-/4µS	?12b	Tos	(BUX99,BUV63,2SC3632,2SC3840)
2SC5209	Si-NPN	Hi-beta,50V,1A,130MHz,B>600	39b	Mit	2SC3727
2SC521(A)	Si-NPN	=2SC519..:70V	23a$	Tos	BD245A,BDV93,BDX93,2SD895..

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2SC5210	Si-NPN	AF/Vid,300/250V,0,1A,80MHz	39b	Mit	BFN18,2SC3380,2SC3515,2SC3554,2SC4189
2SC5211	Si-NPN	GenP,55V,0,4A,150MHz	39b	Mit	BCX55,2SC3444,2SD1006,2SD1767..
2SC5212	Si-NPN	GenP,25V,0,7A,180MHz	39b	Mit	BCX54,2SC3444,2SC4376,2SC4539..
2SC5213	Si-NPN	GenP,120/120V,0,1A,200MHz	39b	Mit	-
2SC5214	Si-NPN	GenP,30V,1A,100MHz	39b	Mit	BCX54..56,2SC3444,2SD1005,2SD1615,..
2SC5216	Si-NPN	VHF/UHF,15V,50mA,1300MHz	35a	Matsushita	BFR53,2SC3014,2SC3773
2SC5217	Si-NPN	Sw,Pow,500/400V,7A,tf=300nS	17c	Mat	2SC3890,2SC4056,2SC4130,2SC4161..
2SC5218	Si-NPN	VHF/UHF,15V,50mA,9GHz	35a	Hitachi	2SC3583,2SC3904,2SC4591
2SC5219	Si-NPN+Diode	Display-HD,1700/-V,8A,50W	?18c	Hit	BUH517D,2SC5143
2SC522(M)	Si-NPN	HF/Sw-Pow,140/100V,1,5A,10W,60MHz	43a$	Tos	(2SC3117,2SD669)
2SC5221	Si-NPN	Sw,Pow,490/490V,0,2A,10W,B>150	30j$	Mat	-
2SC5222	Si-NPN	Sw,Pow,500/500V,0,5A,10W,B>100	30j$	Mat	-
2SC5223	Si-NPN	Sw,Pow,500/500V,1A,10W,B>100	30j$	Mat	-
2SC5224	Si-NPN	Sw,Pow,500/500V,2A,10W,B>100	30j$	Mat	-
2SC5225	Si-NPN	Vid,100V,0,3A,0,625W,1,4GHz	7c	Hit	-
2SC5226	Si-NPN	VHF/UHF,20V,70mA,7GHz	35a(2mm)	Sanyo	BFS520,2SC5085
2SC5226-3	Si-NPN	-	35(2mm)	Sanyo	→2SC5226
2SC5226-4	Si-NPN	-	35(2mm)	Sanyo	→2SC5226
2SC5226-5	Si-NPN	-	35(2mm)	Sanyo	→2SC5226
2SC5227	Si-NPN	-	35	Sanyo	→2SC5227
2SC5227-3	Si-NPN	-	35	Sanyo	→2SC5227
2SC5227-4	Si-NPN	-	35	Sanyo	→2SC5227
2SC5227-5	Si-NPN	-	35	Sanyo	→2SC5227
2SC5228	Si-NPN	-	44	Sanyo	→2SC5228
2SC5228-3	Si-NPN	-	44	Sanyo	→2SC5228
2SC5228-4	Si-NPN	-	44	Sanyo	→2SC5228
2SC5228-5	Si-NPN	-	44	Sanyo	→2SC5228
2SC5229	Si-NPN	-	39	Sanyo	→2SC5229
2SC523	Si-NPN	=2SC522:120/80V	43a$	Tos	(2SC3117,2SD669)
2SC5230	Si-NPN	VHF/UHF,20V,70mA,0,4W,6,5GHz	7f	Sanyo	2SC3355,2SC3507,2SC4968
2SC5231	Si-NPN	VHF/UHF,20V,70mA,7GHz	35a(1,6mm)	Sanyo	2SC4839,2SC5086
2SC5231-C7	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5231
2SC5231-C8	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5231
2SC5231-C9	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5231
2SC5232	Si-NPN	AF,Sw,Mute,15V,0,5A,85/210nS	35	Tos	BSR13,2SC3392,2SC3739
2SC5233	Si-NPN	=2SC5232:	35(2mm)	Tos	2SC4173
2SC5235	Si-NPN	TV/Monitor-HD,1500V,20A,tf<300nS	77j$	Mat	2SC3997,2SC4290A,2SC4897,2SD2356
2SC5237	Si-NPN	Vid-Out,250/250V,0,15A,8W,400MHz	?14b	Hit	2SC4623
2SC5238	Si-NPN	Monitor-HD,Hi-def,1500/800V,50A,160W	77j$	Sanyo	-
2SC5239	Si-NPN	Sw,Pow,Sw-Reg,900/550V,3A,50W,6MHz	17j$	Sak	BUT11A,BUV46A,2SC3148,2SC3150
2SC524(M)	Si-NPN	=2SC522:100/60V	43a$	Tos	(BD139,BD230,BD379,2SD1177..1178)
2SC5241	Si-NPN	Sw-Reg,600/450V,5A,30W,<500/2100nS	17c	Shi	BUT11(A)F,2SC3750,2SC3795,2SC4054,..
2SC5242	Si-NPN	=2SC5200:130W	18j$	Tos	2SC3263
2SC5243	Si-NPN	Monitor-HD,1700V,15A,200W	77j$	Mat	2SC4896,2SC5144
2SC5244	Si-NPN	Monitor-HD,1500V,20A,200W	77j$	Mat	2SC4290A,2SC4897,2SC5142
2SC5244A	Si-NPN	=2SC5244:1600	77j$	-	2SC5057,2SC5144
2SC5245	Si-NPN	VHF/UHF,20V,30mA,11GHz	35a(2mm)	Sanyo	2SC5051,2SC5275
2SC5245-3	Si-NPN	-	35(2mm)	Sanyo	→2SC5245
2SC5245-4	Si-NPN	-	35(2mm)	Sanyo	→2SC5245
2SC5245-5	Si-NPN	-	35(2mm)	Sanyo	→2SC5245
2SC5246	Si-NPN	VHF/UHF,15V,20mA,12GHz	35a(1,6mm)	Hitachi	2SC5139
2SC5247	Si-NPN	VHF/UHF,15V,50mA,13,5GHz	35a(1,6mm)	Hitachi	2SC5139
2SC5248	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,150MHz	17c	Rhm	2SC3298(A,B),2SC3364,2SC4159,2SC4370
2SC5249	Si-NPN	Sw,Pow,Sw-Reg,600/600V,3A,35W,6MHz	17c	Sak	BUT11(A)F,2SC4054,2SC4304,2SD1571,..
2SC525	Si-NPN	=2SC522:70/40V	43a$	Tos	(BD139,BD230,BD377,2SD1177..1178)
2SC5250	Si-NPN+Diode	Display-HD,1500/-V,8A,50W	?18c	Hit	BU2520DF,2SC4763
2SC5251	Si-NPN	Display-HD,1500/800V,12A,50W	?18c	Hit	BU2525AF,2SC4890,2SC5048
2SC5252	Si-NPN	Display-HD,1500/800V,15A,50W	?18c	Hit	2SC4891
2SC5254	Si-NPN	VHF/UHF,15V,40mA,>9GHz	35a	Toshiba	2SC5050
2SC5255	Si-NPN	=2SC5254:	35a(2mm)	Tos	2SC5051
2SC5256	Si-N	=2SC5254:	35a(1,6mm)	Tos	2SC5139,2SC5247
2SC5256F	Si-N	=2SC5254:	flat	Tos	2SC5139,2SC5247
2SC5257	Si-NPN	=2SC5254:	44	Tos	2SC5080
2SC5258	Si-NPN	=2SC5254:	44(2mm)	Tos	2SC4995,2SC5081

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2SC5259	Si-NPN	VHF/UHF, 15V, 15mA, >9GHz	35a	Tos	-
2SC526(M)	Si-NPN	Vid, 165V, 55mA, 0,75W, 250MHz	2a$	Mat,Mic	BF257..259, BF657..659, 2N5058..59
2SC5260	Si-NPN	=2SC5259:	35a(2mm)	Tos	-
2SC5261	Si-N	=2SC5259:	35a(1,6mm)	Tos	2SC5246
2SC5261F	Si-N	=2SC5259:	flat	Tos	2SC5246
2SC5262	Si-NPN	=2SC5259:	44	Tos	2SC5078
2SC5263	Si-NPN	=2SC5259:	44(2mm)	Tos	2SC5079
2SC5264	Si-NPN	Sw, Pow, 1000/450V, 5A, 30W, Inverter Controlled Lighting Applic.	17c	Sanyo	-
2SC5265	Si-NPN	Sw, Pow, 1200/600V, 4A, 30W, Inverter Controlled Lighting Applic.	17c	Sanyo	-
2SC5266	Si-NPN	Sw, Pow, 600/400V, 5A, <700/3000nS	15c	Tos	BUT11(A)F, 2SC3750, 2SC3795, 2SC4056,..
2SC527	Si-NPN	HF, 35V, 10mA, 0,13W, 340MHz	5g	Mat	BF198..199, BF224..225, BF505..
2SC5270	Si-NPN	TV/Monitor-HD, 1500/600V, 12A, 120W	18c	Mat	BU2525AF, 2SC4890, 2SC5251
2SC5270A	Si-NPN	=2SC5270: 1600/600V	18c	-	BU2725AF, BU2727AF
2SC5271	Si-NPN	Sw, Pow, Sw-Reg, 300/200V, 5A, 30W, 10MHz	17c	Sak	2SC3570, 2SC3573, 2SC4073, 2SC4129..
2SC5273	Si-NPN	Sw, Pow, Focus, 1300/1300V, 0,03A, 1,8A	17j$	Hit	2SC3675
2SC5274	Si-NPN	GenP, 150/150V, 0,05A, 120MHz	35(1,6mm)	Rhm	2SD2240(A)
2SC5275	Si-NPN	-	35	Sanyo	→2SC5275
2SC5275-3	Si-NPN	-	35	Sanyo	→2SC5275
2SC5275-4	Si-NPN	-	35	Sanyo	→2SC5275
2SC5275-5	Si-NPN	-	35	Sanyo	→2SC5275
2SC5276	Si-NPN	-	44	Sanyo	→2SC5276
2SC5276-3	Si-NPN	-	44	Sanyo	→2SC5276
2SC5276-4	Si-NPN	-	44	Sanyo	→2SC5276
2SC5276-5	Si-NPN	-	44	Sanyo	→2SC5276
2SC5277	Si-NPN	=2SC5275:	35a(1,6mm)	Sanyo	2SC5139, 2SC5247
2SC5277-D1	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5277
2SC5277-D2	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5277
2SC5277-D3	Si-NPN	-	35(1,6mm)	Sanyo	→2SC5277
2SC5278	Si-NPN	Sw, Pow, 450/400V, 10A, tf=1µS	18j$	Mat	2SC2625, 2SC2740, 2SC3042, 2SC4138..
2SC5279	Si-NPN	Sw, Pow, 600/400V, 2A, <1/3,5µS	15c	Tos	BUT11(A)F, 2SC4052, 2SC4304, 2SD1571,..
2SC528	Si-NPN	GenP, 20V, 0,15A, 0,2W, 100MHz	9b	Hitachi	BC168, BC183, BC238, BC548, 2SD767..
2SC5280	Si-NPN	CRT HD, 1500/600V, 8A, 50W	18c	Tos	BU2508AF, 2SC3896, 2SC3886A, 2SC4758,..
2SC5281	Si-NPN	Sw, Pow, 800/500V, 10A, tf=300nS	18c	Mat	BUP23CF, BUV48AF, BUW13AF, 2SC4430
2SC5282	Si-NPN	Sw, Pow, 900/800V, 4A, Tf=300nS	18c	Mat	BUW11AF, 2SC4300, 2SC4428, 2SC4586
2SC5283	Si-NPN	Sw, Pow, 1000/800V, 5A, 80W, <1/3µS	18c	Mat	BUW11AF, 2SC4428, 2SC4584, 2SC4882
2SC5284	Si-NPN	Sw, Pow, 1200/800V, 10A, 80W, <0,7/3,3µS	18c	Mat	BUH715, 2SC3897, 2SC4199A, 2SC4585
2SC5285	Si-NPN	Sw, Pow, -/500V, 0,5A	30j$	Mat	2SC3129, 2SC3588, 2SC4499
2SC5287	Si-NPN	Sw, Pow, Sw-Reg, 900/550V, 5A, 80W, 6MHz	18j$	Sak	BUW11A, BUW131A, 2SC3636, 2SC3642
2SC5288	Si-NPN	UHF, DECT 1,9GHz, 9V, 0,15A	44ze	Nec	-
2SC5288-KB	Si-NPN	-	44	Nec	→2SC5288
2SC5289	Si-NPN	UHF, DECT 1,9GHz), 9V, 0,3A	44ze	Nec	-
2SC5289-KB	Si-NPN	-	44	Nec	→2SC5289
2SC529	Si-NPN	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hitachi	BC183, BC238, BC548, BF254..255..
2SC5291	Si-NPN	=2SC3902: 1,5W	?12b	Sanyo	(→2SC3902)
2SC5294	Si-NPN	TV/Monitor-HD, 1500/600V, 20A, 120W	18c	Mat	-
2SC5294A	Si-NPN	=2SC5294: 1600/600V	18c	-	-
2SC5295	Si-NPN	SHF, 15V, 65mA, 9GHz	35a(1,6mm)	Mat	2SC5139, 2SC5247
2SC5296	Si-NPN+Diode	=2SC5297: Int. Damper-Diode	18c	Sanyo	BU2520DF, 2SC4124, 2SC4763, 2SC5149
2SC5297	Si-NPN	Monitor-HD, Hi-def, 1500/800, 8A, 60W	18c	Sanyo	2SC3896, 2SC4758, 2SC5148, 2SC5067
2SC5298	Si-NPN+Diode	=2SC5299: Int. Damper-Diode	18c	Sanyo	BU2520DF, 2SC4125, 2SC4878
2SC5299	Si-NPN	Monitor-HD, Hi-def, 1500/800, 10A, 70W	18c	Sanyo	BU2520AF, BUH715, 2SC4589, 2SC5068
2SC53	Si-NPN	HF-Dr, 25V, 0,1A, 0,6W, 300MHz	2a$	Fui	BFW16..17, BFX55
2SC530	Si-NPN	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hitachi	BC183, BC238, BC548, BF254..255..
2SC5300	Si-NPN	CRT HD, Hi-def, 1500/800V, 20A, 75W	18c	Sanyo	2SC5516
2SC5301	Si-NPN	CRT HD, Hi-def, 1500/800V, 20A, 120W	77j$	Sanyo	2SC3997, 2SC4290A
2SC5302	Si-NPN	CRT HD, Hi-def, 1500/800V, 15A, 75W	18c	Sanyo	2SC4891, 2SC5252
2SC5303	Si-NPN	CRT HD, 1500/800V, 25A, 140W	77j$	Sanyo	2SC3998, 2SC5047
2SC5304(LS)	Si-NPN	Sw-Reg, 1000/450V, 7A, 35W, Tf<150nS, Inverter Lighting Application	17c	Sanyo	BUF405AFI, BUT12AF
2SC5305(LS)	Si-NPN	Sw-Reg, 1200/600V, 6A, 35W, Tf<150nS, Inverter Lighting Application	17c	Sanyo	BUT18AF, BUV46AFI
2SC5306	Si-NPN	Sw, Pow, HD, 1500/800V, 20A, Tf<300nS	18c	Hit	-
2SC5307	Si-NPN	Sw, 400/400V, 0,05A	39b	Tos	2SC4548, 2SD2413
2SC5309	Si-NPN	TV/Monitor-HD, 1700V, 10A, tf<200	18c	Mat	BU2722AF, 2SC5150
2SC531	Si-NPN	HF, 30V, 0,1A, 0,1W, 230MHz	9b	Hitachi	BC183, BC238, BC548, BF254..255..
2SC5310	Si-NPN	GenP, Lo-sat, 30V, 1A, >150MHz	35a	Sanyo	BCW65..66, 2SC3265

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2SC5310-5	Si-NPN	-	35	Sanyo	→2SC5310
2SC5310-6	Si-NPN	-	35	Sanyo	→2SC5310
2SC5315	Si-NPN	UHF/SHF,8V,20mA,>9GHz	35a	Tos	-
2SC5316	Si-NPN	=2SC5315:	35a(2mm)	Tos	-
2SC5317	Si-N	=2SC5315:	35a(1,6mm)	Tos	2SC5246
2SC5317F	Si-N	=2SC5315:	flat	Tos	2SC5246
2SC5318	Si-NPN	=2SC5315: >13GHz	44	Tos	2SC5078
2SC5319	Si-NPN	=2SC5315: 13GHz	44(2mm)	Tos	2SC5079
2SC532	Si-NPN	FM-IF,30V,0,1A,0,1W,230MHz	9b	Hitachi	BF240..241,BF254..255,BF594..595,..
2SC5320	Si-NPN	UHF/SHF,8V,10mA,>9GHz	35a	Tos	-
2SC5321	Si-NPN	=2SC5320:	35a(2mm)	Tos	-
2SC5322	Si-N	=2SC5320:	35a(1,6mm)	Tos	2SC5246
2SC5322F	Si-N	=2SC5320:	flat	Tos	2SC5246
2SC5323	Si-NPN	=2SC5320:	44	Tos	2SC5078
2SC5324	Si-NPN	=2SC5320:	44(2mm)	Tos	2SC5079
2SC5327	Si-NPN	GenP,40V,0,5A,0,5W,300MHz	7	-	BC337,BC635,2SD863,2SD1225..26,..
2SC5328	Si-NPN	GenP,60V,0,15A,0,4W,>80MHz	7	-	BC174,BC182,BC546,2SD767..
2SC5329	Si-NPN	GenP,35V,0,8A,0,625W,130MHz	7	-	BC337,BC635,2SD863,2SD1225..26,..
2SC533	Si-NPN	FM-IF,230MHz	9b	Hitachi	BF240..241,BF254..255,BF594..595,..
2SC5330	Si-NPN	HF,30V,0,02A,0,4W,>300MHz	7	-	BF198,BF225,BF310,BF367,BF596..
2SC5331	Si-NPN	CTV/Display-HD Hi-res,64kHz,1500/600V,15A,180W	77j$	Tos	BU2530AL,2SC3996,2SC4289A
2SC5332	Si-NPN	CTV/Display-HD Hi-res,64kHz,1700/800V,10A,200W	77j$	Tos	2SC4532,2SC4880,2SC5058
2SC5333	Si-NPN	Sw,Pow,Sw-Reg,300/300V,2A,35W,10MHz	17c	Sak	2SC3309,2SC3560..61,2SC3868,2SC3969
2SC5335	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,60V,0,7A,1W,200MHz,B=400..2000	9c	Mat	2SD1582,2SD1779
2SC5336	Si-NPN	UHF/CATV,20V,0,1A,6,5GHz	39s	Nec	-
2SC5336-RE	Si-NPN	-	39	Nec	→2SC5336
2SC5336-RF	Si-NPN	-	39	Nec	→2SC5336
2SC5336-RH	Si-NPN	-	39	Nec	→2SC5336
2SC5337	Si-NPN	UHF/CATV,30V,0,25A	39s	Nec	-
2SC5337-QQ	Si-NPN	-	39	Nec	→2SC5337
2SC5337-QR	Si-NPN	-	39	Nec	→2SC5337
2SC5337-QS	Si-NPN	-	39	Nec	→2SC5337
2SC5338	Si-NPN	UHF/CATV,25V,0,15A,6GHz	39s	Nec	-
2SC5338-SE	Si-NPN	-	39	Nec	→2SC5338
2SC5338-SF	Si-NPN	-	39	Nec	→2SC5338
2SC5338-SH	Si-NPN	-	39	Nec	→2SC5338
2SC5339	Si-NPN+Diode	CTV/Display-HD hi-res,31,5kHz,1500/600V,7A,50W	18c	Tos	BU2520DF,2SC3892A,2SC4123,2SC4762,+
2SC534	Si-NPN	FM-Preamp/Mix/Osc,30V,0,1A,0,1W,230MHz	9b	Hitachi	BF240,BF255,BF495,BF595..
2SC5340	Si-NPN	Sw,-/300V,0,1A,140MHz	78	Mat	(2SC3789..90,2SC4217,2SC4828)
2SC5341	Si-NPN	Display-Driver 110V,0,15A,350MHz	78	Mat	(2SC3598..99,2SC3953..54)
2SC5346	Si-NPN	GenP,150/150V,0,05A,1W,160MHz	9c	Mat	2SC2362K,2SC2632,2SC3800,2SD2030..
2SC5347	Si-NPN	VHF/UHF,20V,150mA,4,7GHz	39b	Sanyo	2SC4703
2SC5347-D	Si-NPN	-	39	Sanyo	→2SC5347
2SC5347-E	Si-NPN	-	39	Sanyo	→2SC5347
2SC5347-F	Si-NPN	-	39	Sanyo	→2SC5347
2SC535	Si-NPN	FM/VHF-Pre/Mix/Osc,700MHz	9b,7c	Hit	BF225,BF310,BF314,BF502,BF505..
2SC5350	Si-NPN	Hi-beta,Lo-sat,50V,5A,150MHz	39b	Tos	-
2SC5351	Si-NPN	Sw,650/450V,2A,1,3W,<-/2,3µS	?12b	Tos	(BUV94)
2SC5352	Si-NPN	Sw,Pow,600/400V,10A,80W,<-/2,3µS	18j$	Tos	BUP23,2SC3450,2SC3831,2SC4058..
2SC5353	Si-NPN	Sw,Pow,900/800V,3A,25W,<-/4,5µS	17c	Tos	2SC3559,2SC4304,2SC4517,2SC4471A..
2SC5354	Si-NPN	Sw,Pow,900/800V,5A,100W,<-/4,5µS	18j$	Tos	BUW11A,2SC3535,2SC3636,2SC3796A..
2SC5355	Si-NPN	Sw,Pow,600/400V,5A,25W,<-/2,3µS	30j$	Tos	BUD630
2SC5356	Si-NPN	Sw,Pow,900/800V,3A,25W,<-/4,5µS	30j$	Tos	BUD636A
2SC5357	Si-NPN	Sw,650/450V,2A,<-/2,3µS	39b	Tos	-
2SC5358	Si-NPN	AF,Sw-Pow,230/230V,15A,150W,30MHz	18j$	Tos	2SC2944,2SC3263
2SC5359	Si-NPN	=2SC5358: 180W	77j$	Tos	2SC4029,2SC5200
2SC536(..P..)	Si-NPN	GenP,40..55V,0,1A,0,2W,180MHz	?7c,7c	Say,Mic	BC183,BC237,BC547,BF254..255..
2SC5360	Si-NPN	Vid-Out,300/300V,0,15A,12,5W,>40MHz	17c	Tos	2SC3565,2SC3942,2SC3945,2SC4075
2SC5361	Si-NPN	Sw,Pow,900/800V,3A,40W,<-/4,5µS	30j$	Tos	2SC4224,2SC4602,(2SC3050,2SC3457)
2SC5363	Si-NPN	SHF,9V,30mA,10GHz	35(1,6mm)	Mat	2SC4840,2SC5091
2SC5368	Si-NPN	Sw,650/450V,2A,10W,<-/2,3µS	14b	Tos	-
2SC5369	Si-NPN	SHF,9V,30mA,14GHz	46(EEBEEC)	Nec	-
2SC5369-FB	Si-NPN	-	46	Nec	→2SC5369
2SC537(FP)	Si-NPN	=2SC536: 20V	?7c,7c	Say,Mic	BC183,BC238,BC548,BF254..255..

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2SC5370	Si-NPN	Lo-sat,60V,12A,30W,90MHz	17c	Sak	2SC3709..10,2SC4065,2SC4595,2SD2219
2SC5373	Si-NPN	UHF/SHF,9V,50mA,15GHz	35a(2mm)	Sanyo	2SC5051
2SC5374	Si-NPN	VHF/UHF,20V,100mA,5,2GHz	35a(1,6mm)	Sanyo	-
2SC5375	Si-NPN	-	35(2mm)	Sanyo	→2SC5375
2SC5376	Si-NPN	AF,Sw,Mute,15V,0,4A,85/210nS	35(1,6mm)	Tos	-
2SC5378	Si-NPN	UHF/SHF,15V,80mA,7GHz	35(2mm)	Mat	BFS520,BFS540,2SC5085
2SC5378-Q	Si-NPN	-	35(2mm)	Mat	→2SC5378
2SC5378-R	Si-NPN	-	35(2mm)	Mat	→2SC5378
2SC5378-S	Si-NPN	-	35(2mm)	Mat	→2SC5378
2SC5379	Si-NPN	-	35(1,6mm)	Mat	→2SC5379
2SC5379-Q	Si-NPN	-	35(1,6mm)	Mat	→2SC5379
2SC5379-R	Si-NPN	-	35(1,6mm)	Mat	→2SC5379
2SC5379-S	Si-NPN	-	35(1,6mm)	Mat	→2SC5379
2SC538(Z)	Si-NPN	GenP,25V,0,05A,0,3W,150MHz	2a	Mat,Mic	BC168,BC183,BC238,BC548,2SC1890+
2SC5380(A)	Si-NPN	TV/Monitor-HD,1500/600,16A,100W	18c	Mat	2SC4891,2SC5252
2SC5381	Si-NPN	TV/Monitor-HD,1500,16A,150W	77j$	Mat	BU2530AL,2SC3996,2SC4289A
2SC5383	Si-NPN	GenP,50V,0,2A,200MHz	-	Mit	-
2SC5384	Si-NPN	FM/HF/AF,30V,30mA,200MHz	-	Mit	-
2SC5386	Si-NPN	CTV/Display-HD Hi-res,64kHz,1500/600V,8A,50W	18c	Tos	2SC3886A,2SC3896,2SC4758,2SC5148
2SC5387	Si-NPN	CTV/Display-HD Hi-res,64kHz,1500/600V,10A,50W	18c	Tos	BU2520AF,BUH715,2SC4542,2SC4759
2SC5388	Si-NPN+Diode	TV/CRT-HD,1500/700V,5A,50W,B>100	18c	Sanyo	-
2SC5389	Si-NPN	TV/Monitor-HD,1700V,6A,tf<800nS	18c	Mat	BUH417,BUH517,2SC4761,2SC4796
2SC538A(AZ)	Si-NPN	=2SC538:45V	2a	-	BC167,BC182,BC237,BC547,2SC1890+
2SC539(Z)	Si-NPN	=2SC538:ra	2a	Mat	BC169,BC184,BC239,BC549,2SC2675+
2SC5390	Si-NPN	Vid-Out,Hi-def,110V,0,2A,7W,>1GHz	14b	Hit	-
2SC5392	Si-NPN	Sw,Pow,800/500V,1,5A,25W,<1/3,3µS	17c	Mat	BUX84F..85F,2SC3352,2SC3794,2SD1571+
2SC5393	Si-NPN	Sw,Pow,600/400V,5A,40W,<-/2,3µS	17c	Mat	BUT21BF,2SC4054,2SC5172
2SC5394	Si-NPN	GenP,LN,50V,0,2A,0,3W,200MHz	41	Mit	BC414,BC550,2SC2240,2SC2459..
2SC5395	Si-NPN	GenP,50V,0,2A,0,3W,200MHz	41	Mit	BC414,BC550,2SC2240,2SC2459..
2SC5396	Si-NPN	HF/FM,25V,20mA,470MHz	41	Mit	BF225,BF310,BF314,BF502,BF505..
2SC5397	Si-NPN	HF/IF,FM,30V,30mA,200MHz	41	Mit	BF240..241,BF254..255,BF594..595,..
2SC5398	Si-NPN	GenP,30V,1A,0,9W,100MHz	41	Mit	BC635,BC637,2SD667,2SC1616(A)..
2SC54	Si-NPN	=2SC52:0,3W	2a$	-	BFX59,(BFW16..17,BFX55)
2SC540	Si-NPN	Min,GenP,LN,30V,0,1A,0,15W,100MHz	24b	Nec	(BC169,BC184,BC239,BC549,2SC2675,..)
2SC5404	Si-NPN	HD,1500/600V,9A,50W	18c	Tos	BU2520AF,BUH715,2SC4542,2SC4759
2SC5405	Si-NPN	Hi-beta,-/60V,3A	17c	Mat	2SD1944,2SD2092,2SC2156,2SD2396..
2SC5406(A)	Si-NPN	TV/Monitor-HD,1500/600,14A,100W	18c	Mat	2SC4891,2SC5252
2SC5407	Si-NPN	TV/Monitor-HD,1700/600,16A,100W	18c	Mat	-
2SC5408	Si-NPN	SHF,5V,10mA,17GHz	46(EEBEEC)	Nec	-
2SC5409	Si-NPN	SHF,5V,30mA,16GHz	46(EEBEEC)	Nec	-
2SC5409-FB	Si-NPN	-	46	Nec	→2SC5409
2SC541	Si-NPN	VHF-A/Dr,50V,1A,Pq=4W(175MHz)	2a$	Fui	BFS23
2SC5410(A)	Si-NPN	TV/Monitor-HD,1500/600V,25A,200W	77j$	Mat	2SC3998,2SC4789,2SC5047
2SC5411	Si-NPN	CTV/Display-HD Hi-res,64kHz,1500/600V,14A,60W	18c	Tos	2SC4891,2SC5252
2SC5412	Si-NPN	TV/Monitor-HD,1700/600V,4A,50W	18c	Mat	2SC4761,2SC4796,2SC4806
2SC5413	Si-NPN	TV/Monitor-HD,1700/600V,20A,200W	77j$	Mat	2SC5057,2SC5144
2SC5414	Si-NPN	UHF,20V,0,1A,0,4W,>5GHz	7f(9mm)	Sanyo	-
2SC5415	Si-NPN	-	39	Sanyo	→2SC5415
2SC5415-E	Si-NPN	-	39	Sanyo	→2SC5415
2SC5415-F	Si-NPN	-	39	Sanyo	→2SC5415
2SC5416(LS)	Si-NPN	Sw-Reg,1000/450V,4A,25W,tf<150ns,Inv.Lighting Appl.	17c	Sanyo	BUT11AF,2SC4518A
2SC5417LS	Si-NPN	Sw-Reg,1200/600V,3A,25W,tf<150ns,Inv.Lighting Appl.	17c	Sanyo	BU1706AX
2SC5418	Si-NPN	TV/Monitor-HD,1700/600V,20A,100W	18c	Mat	-
2SC5419	Si-NPN	HF,Vid,300/300V,70mA,1W,50MHz	9c	Mat	BF420A,BF299,2SC3672,2SC4490..
2SC542	Si-NPN	VHF-Pow,65V,1,5A,Pq=6W(175MHz)	49a	Fui	BLY60,2N3632
2SC5420	Si-NPN	Sw-Reg,1000/450V,5A,50W,tf<150ns,B=6000>2000,Inv.Lighting Appl.	30j$	Sanyo	(BUT11A,BUT18A,BUV46A,2SC3050)
2SC5421	Si-NPN	HD,1500/600V,15A,180W	77j$	Tos	BU2530AL,2SC3996,2SC4289A
2SC5422	Si-NPN	HD,1700/600V,15A,200W	77j$	Tos	2SC4896
2SC5423	Si-NPN	TV/Monitor-HD,1700/600V,15A,100W	18c	Mat	2SC5045
2SC5428	Si-NPN	TV/Monitor-HD,1500/600V,25A,100W	18c	Mat	-
2SC543	Si-NPN	VHF-Pow,65V,3A,Pq=14,5W(175MHz)	49a	Fui	BLY35,2N3632
2SC5431	Si-NPN	Mobile Comm.,VCO,1GHz,5V,5mA	35(1,6mm)	Nec	-
2SC5431-EB	Si-NPN	npn RF fT 4.3GHz 12V 60mA	-	Nec	-
2SC5431-FB	Si-NPN	npn RF fT 4.3GHz 12V 60mA	-	Nec	-

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2SC5432	Si-NPN	Mobile Comm., VCO, 1GHz, 3V, 7mA	35(1,6mm)	Nec	-
2SC5432-EB	Si-NPN	npn RF fT 4.5GHz 12V 100mA	-	Nec	-
2SC5432-FB	Si-NPN	npn RF fT 4.5GHz 12V 100mA	-	Nec	-
2SC5433	Si-NPN	Mobile Comm., VCO, 1GHz, 3V, 7mA	35(1,6mm)	Nec	-
2SC5434	Si-NPN	Mobile Comm., VCO, 2GHz, 3V, 5mA	35(1,6mm)	Nec	-
2SC5435	Si-NPN	Mobile Comm., VCO, 2GHz, 3V, 3mA	35(1,6mm)	Nec	-
2SC5435-EB	Si-NPN	npn RF fT 12GHz 9V 30mA	-	Nec	-
2SC5435-FB	Si-NPN	npn RF fT 12GHz 9V 30mA	-	Nec	-
2SC5436	Si-NPN	Mobile Comm., VCO, 2GHz, 2V, 3mA	35(1,6mm)	Nec	-
2SC5436-EB	Si-NPN	npn RF fT 14GHz 5V 30mA	-	Nec	-
2SC5436-FB	Si-NPN	npn RF fT 14GHz 5V 30mA	-	Nec	-
2SC5437	Si-NPN	Mobile Comm., VCO, 2GHz, 1V, 3mA	35(1,6mm)	Nec	-
2SC5439	Si-NPN	Sw, Pow, 1000/450V, 8A, 30W, <-/2,15µS	17c	Tos	BUF405AFI, BUT12AF, MJF18008, MJF18206
2SC544	Si-NPN	HF/AF, 40V, 0,03A, 0,15W, 350MHz	??c	Sanyo	BF198..199, BF224..225, BF505..
2SC5440	Si-NPN	TV/Monitor-HD, 1500/600V, 15A, 60W	18c	Mat	2SC4891, 2SC5252
2SC5441(A)	Si-NPN	TV/Monitor-HD, 1500/600V, 15A, 100W	18c	Mat	2SC4891, 2SC5252
2SC5442(A)	Si-NPN	TV/Monitor-HD, 1500/600V, 15A, 100W	77j$	Mat	BU2530AL, 2SC3996, 2SC4289A, 2SC5046
2SC5443	Si-NPN	CRT HD, Hi-def, 1500/800V, 20A, 180W	77j$	Sanyo	2SC3997, 2SC4290A, 2SC4897
2SC5444	Si-NPN	CRT HD, Hi-def, 1500/800V, 25A, 210W	77j$	Sanyo	2SC3998, 2SC4789, 2SC5047
2SC5445	Si-NPN	HD, 1500/600V, 20A, 200W	77j$	Tos	2SC4290A, 2SC4897, 2SC5142, 2SC5244..
2SC5446	Si-NPN	HD, 1700/600V, 18A, 200W	77j$	Tos	2SC5057, 2SC5144
2SC5447	Si-NPN	HD, 1500/700V, 8A, 50W	18c	Hit	2SC3896, 2SC4758, 2SC5148
2SC5448	Si-NPN	HD, 1500/700V, 10A, 50W	18c	Hit	BU2522AF, 2SC4542, 2SC4759, 2SC5129
2SC5449	Si-NPN	HD, 1500/700V, 12A, 50W	18c	Hit	BU2527AF, 2SC4692, 2SC4890, 2SC5048
2SC545	Si-NPN	HF/AF, 20V, 0,03A, 0,15W, 350MHz	??c	Sanyo	BF198..199, BF224..225, BF505..
2SC5450	Si-NPN	CRT HD, Hi-def, 1600/800V, 10A, 70W	18c	Sanyo	BU2727AF, 2SC4879, 2SC5044
2SC5451	Si-NPN	CRT HD, Hi-def, 1600/800V, 15A, 75W	18c	Sanyo	2SC5045
2SC5452	Si-NPN	CRT HD, Hi-def, 1600/800V, 20A, 75W	18c	Sanyo	-
2SC5453	Si-NPN	CRT HD, Hi-def, 1600/800V, 25A, 210W	77j$	Sanyo	2SC5047, 2SC5244A
2SC5454	Si-NPN	BS Tuner, Buffer Amp, 2GHz, 3V, 5mA	44	Nec	-
2SC5455	Si-NPN	BS Tuner, Buffer Amp, 2GHz, 3V, 7mA	44	Nec	-
2SC5457(Z)	Si-NPN	Sw, Pow, 500/400V, 3A, 30W, <1/3,3µS	30j$	Mat	2SC4346
2SC5458	Si-NPN	Sw, Pow, 600/400V, 0,8A, 10W, <-/2,3µS	30j$	Tos	2SC3632
2SC5459	Si-NPN	Sw, Pow, 600/400V, 3A, 25W, <-/2,3µS	17c	Tos	2SC4052, 2SC5249
2SC546	Si-NPN	HF/AF, 30V, 0,03A, 0,15W, 600MHz	??c	Sanyo	BF198..199, BF224..225, BF505..
2SC5460	Si-NPN	Sw, Pow, 800/800V, 50mA, 10W, 5,5MHz	14b	Tos	-
2SC5461	Si-NPN	HD, 1500/700V, 15A, 50W	18c	Hit	2SC4891, 2SC5252
2SC5462	Si-NPN	HD, 1500/700V, 20A, 50W	18c	Hit	-
2SC5463	Si-NPN	VHF/UHF, 20V, 60mA	35a(2mm)	Toshiba	2SC4571, 2SC4780, 2SC4905..06, 2SC5110
2SC5464	Si-NPN	=2SC5463:	35a(1,6mm)	Tos	2SC5111, 2SC5136, 2SC5141
2SC5465	Si-NPN	Sw, Pow, 900/800V, 0,8A, 20W, <-/3,5µS	30j$	Tos	2SC3405, 2SC3489
2SC5466	Si-NPN	Sw, Pow, 800/800V, 50mA, 10W, 5,5MHz	17c	Tos	2SC4630, 2SC4686(A)
2SC5468	Si-NPN	Vid-Out, 120V, 0,3A, 8W, 400MHz	14b	Tos	2SC4565, (2SC3599)
2SC5469	Si-NPN	HD, 1500/700V, 15A, 125W	18c($)	Hit	BUH1015, BUH1215
2SC547(D)	Si-NPN	VHF-A/Dr, 65V, 1A, Pq>2,5W(175MHz)	2a$	Tos	BFS23, BLY34
2SC5470	Si-NPN	HD, 1500/700V, 20A, 150W	18c($)	Hit	-
2SC5472	Si-NPN	SHF, 9V, 30mA, 12GHz	35a(2mm)	Mat	-
2SC5473	Si-NPN	SHF, 9V, 30mA, 12GHz	44(2mm)	Mat	-
2SC5474	Si-NPN	SHF, 9V, 30mA, 12GHz	35a(1,6mm)	Mat	-
2SC5476	Si-N-Darl+Di	Z-Di(B→C), 85/85V, 3A, 20W, 50MHz	17c	Sanyo	2SD1890, 2SD2129, 2SD2257
2SC5477	Si-NPN	HF, 30V, 50mA, >600MHz	35	Mit	BF547, BFS17, 2SC3077, 2SC3161
2SC5478	Si-NPN	TV/Monitor-HD, 1700/600V, 14A, 60W	18c	Mat	-
2SC548	Si-NPN	VHF-A/Dr, 36V, 0,5A, Pq>1W(175MHz)	2a$	Tos	BFS22, BFQ42, BFW46, MRF237, 2N3924
2SC5482	Si-NPN	AF-Pow, Lo-sat, 60V, 1A, 0,6W, 120MHz	41	Mit	2SC4485..86, 2SD1207, 2SD1835, 2SD2181
2SC5484	Si-NPN	Hi-beta, Lo-sat, 30V, 1,5A, 0,6W, 130MHz, B=400..3000	41	Mit	2SC3225, 2SC3246, 2SC4389
2SC5485	Si-NPN	AF-Pow, 25V, 0,7A, 0,6W, 180MHz	41	Mit	BC337..338, 2SC4485, 2SD2322S..
2SC5486	Si-NPN	AF-Out, 15V, 5A, 0,6W, 135MHz	41	Mit	2SC4781, 2SD1951, 2SD1960..
2SC5488	Si-NPN	VHF/UHF LN, 20V, 70mA, >5GHz	35a(1,4mm)	Sanyo	-
2SC5489	Si-NPN	VHF/UHF LN, 16V, 50mA, 9GHz	35a(1,4mm)	Sanyo	-
2SC549	Si-NPN	VHF-Pow, 65V, 1,5A, Pq>5W(175MHz)	49a	Tos	BLY35, 2N3632
2SC5497	Si-NPN	VHF/UHF, 8V, 15mA	44(2mm)	Tos	-
2SC55	Si-NPN	=2SC52: 0,36W	2a$	-	BFX59, (BFW16..17, BFX55)
2SC550	Si-NPN	VHF-Pow, 36V, 1,5A, Pq>4W(175MHz)	49a	Tos	BLW35, BLY58, 2N3927
2SC5501	Si-NPN	VHF/UHF LN, 20V, 70mA, >5GHz	44ze(2mm)	Sanyo	2SC4842, 2SC5088

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2SC5501-4	Si-NPN	-	44(2mm)	Sanyo	→2SC5501
2SC5501-5	Si-NPN	-	44(2mm)	Sanyo	→2SC5501
2SC5502	Si-NPN	VHF/UHFLN,20V,100mA,>6GHz	44ze(2mm)	Sanyo	2SC5012
2SC5502-4	Si-NPN	-	44(2mm)	Sanyo	→2SC5502
2SC5502-5	Si-NPN	-	44(2mm)	Sanyo	→2SC5502
2SC5503	Si-NPN	VHF/UHFLN,16V,50mA,9GHz	44ze(2mm)	Sanyo	2SC4992,2SC4995,2SC5081
2SC5503-4	Si-NPN	VHF/UHFLN,16V,50mA,9GHz	44(2mm)	Sanyo	→2SC5503
2SC5503-5	Si-NPN	VHF/UHFLN,16V,50mA,9GHz	44(2mm)	Sanyo	→2SC5503
2SC5504	Si-NPN	UHF/SHFLN,20V,30mA,>8GHz	44ze(2mm)	Sanyo	2SC4995,2SC5081
2SC5504-4	Si-NPN	UHF/SHFLN,20V,30mA,>8GHz	44(2mm)	Sanyo	→2SC5504
2SC5504-5	Si-NPN	UHF/SHFLN,20V,30mA,>8GHz	44(2mm)	Sanyo	→2SC5504
2SC5506	Si-NPN	CRT HD,Hi-def,1600/800V,20A,180W	77jS	Sanyo	2SC5047,2SC5144
2SC5508	Si-NPN	RF,LN,15V,35mA,115mW,25GHz,B=50..100	44(2mm)	Nec	-
2SC5509	Si-NPN	RF,LN,15V,100mA,190mW,15GHz,B=50..400	44(2mm)	Nec	-
2SC551	Si-NPN	VHF-Pow,65V,3A,Pq>13,5W(175MHz)	49a	Tos	BLY35,2N3632
2SC5511	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,150MHz,TV Velocity Modulation	17c	Rhm	2SC3298,2SC3364,2SC4159,2SC4370,+
2SC5513	Si-NPN	TV/Monitor-HD,1500/600V,11A,40W	18c	Mat	BU2520AF,BUH715,2SC4542,2SC4759
2SC5514	Si-NPN	TV/Monitor-HD,1500/600V,13A,50W	18c	Mat	2SC4891,2SC5252
2SC5515	Si-NPN	TV/Monitor-HD,1500/600V,17A,65W	18c	Mat	-
2SC552	Si-NPN	VHF-Pow,36V,3A,Pq>12W(175MHz)	49a	Tos	BLW36
2SC5525	Si-NPN	Sw,Pow,Lo-sat,100/60V,5A,25W,120MHz	17c	Rhm	2SC3540,2SC3691,2SC4549..50,2SC4596
2SC5526	Si-NPN	Sw,Pow,Lo-sat,100/60V,12A,25W,80MHz	17c	Rhm	2SC3694,2SC4552,2SC4595
2SC553	Si-NPN	UHF-Pow,65V,3A,Pq>10W(175MHz)	49a	Tos	-
2SC5531	Si-NPN	Sw,Pow,400/400V,2A,30W,<1/3,5µS	30jS	Rhm	2SC3403,2SC4754,2SC5104
2SC5532	Si-NPN	Sw,Pow,400/400V,5A,30W,<1/3,5µS	17c	Rhm	2SC3869,2SC4073,2SC4129,2SC4371..
2SC5534	Si-NPN	UHF/SHFLN,9V,30mA,>10GHz	44ze(2mm)	Sanyo	2SC4995,2SC5014,2SC5081
2SC5536	Si-NPN	VHFLN,20V,50mA,>1GHz	35a(1,4mm)	Sanyo	-
2SC5537	Si-NPN	VHF/UHF,12V,15mA,5GHz	35a(1,4mm)	Sanyo	-
2SC5538	Si-NPN	VHF/UHF,20V,100mA,>3GHz	35a(1,4mm)	Sanyo	-
2SC5539	Si-NPN	VHF/UHF,20V,100mA,>6GHz	35a(1,4mm)	Sanyo	-
2SC554	Si-NPN	UHF-A/Dr/Out,36V,0,5A,400MHz	2a$	Tos	BLX65
2SC5540	Si-NPN	UHF/SHFLN,16V,20mA,10GHz	35a(1,4mm)	Sanyo	-
2SC5541	Si-NPN	UHF/SHFLN,9V,30mA,>10GHz	35a(1,4mm)	Sanyo	-
2SC5543	Si-NPN	VHF/UHFLN,15V,20mA,>5,5GHz	44(2mm)	Hit	2SC4843,2SC5013,2SC5093
2SC5544	Si-NPN	VHF/UHFLN,15V,50mA,>3GHz	44(2mm)	Hit	2SC4992,2SC4995,2SC5081
2SC5545	Si-NPN	UHF,LN,15V,50mA,>10GHz	44	Hit	2SC5081
2SC5546	Si-NPN	TV/Monitor-HD,1700/600V,13A,70W	18c	Mat	-
2SC5547	Si-NPN	VHF/UHF,20V,50mA,>3,5GHz	39b	Mit	2SC4643
2SC5548	Si-NPN	Sw,Pow,600/370V,2A,15W,<-/3,3µS	30jS	Tos	BUD600
2SC5548A	Si-NPN	=2SC5548:600/400V	30jS	-	BUD600
2SC5549	Si-NPN	400/400V,1A,0,9W,<-/5,3µS	7c(9mm)	Tos	-
2SC555	Si-NPN	UHF-A/Dr/Out,55V,0,4A,Pq>1W(400MHz)	2a$	Tos	BFR97
2SC5550	Si-NPN	=2SC5549:10W	14b	Tos	(BD410)
2SC5551	Si-NPN	VHF/UHF,40V,0,3A,3,5GHz	39b	Sanyo	-
2SC5551-E	Si-NPN	-	39	Sanyo	→2SC5551
2SC5551-F	Si-NPN	-	39	Sanyo	→2SC5551
2SC5552	Si-NPN	TV/Monitor-HD,1700/600V,16A,65W	18c	Mat	-
2SC5553	Si-NPN	TV/Monitor-HD,1700/600V,22A,70W	18c	Mat	-
2SC5554	Si-NPN	VHF/UHFLN,15V,20mA,>3,5GHz	44(2mm)	Hit	2SC4813,2SC5013,2SC5093
2SC5555	Si-NPN	VHF/UHFLN,15V,50mA,>6GHz	44(2mm)	Hit	2SC4992,2SC4995,2SC5081
2SC556	Si-NPN	UHF-A/Dr,40V,0,4A,850MHz	2a$	Tos	BFR97,2N3866
2SC5563	Si-NPN	TV,Dyn.Focus,1500/1500V,20mA,10W	17c	Tos	2SC4633,2SC4635,2SC5022
2SC5564	Si-NPN	Lo-sat,15V,6A,380MHz,30/205nS	39b	Sanyo	-
2SC5565	Si-NPN	Lo-sat,40V,5A,420MHz,30/315nS	39b	Sanyo	2SD2098,2SD2402,2SD2540
2SC5566	Si-NPN	Lo-sat,60V,4A,400MHz,35/320nS	39b	Sanyo	2SD1628,2SD2425
2SC5567	Si-NPN	Lo-sat,15V,9A,280MHz,30/205nS	39b	Sanyo	-
2SC5568	Si-NPN	Lo-sat,40V,8A,320MHz,30/335nS	39b	Sanyo	-
2SC5569	Si-NPN	Lo-sat,60V,7A,330MHz,30/445nS	39b	Sanyo	-
2SC557	Si-NPN	VHF-Pow,40V,2A,20W,350MHz	49a	Tos	BLY36,BLY79
2SC5570	Si-NPN	TV/Monitor-HD,1700/800V,28A,220W	77jS	Mat	-
2SC5574	Si-NPN	AF-Pow,100V,4A,30W,10MHz	17c	Rhm	2SC3475,2SC3851A,2SD1586,2SD2468..
2SC5575	Si-NPN	Sw-Reg,lo-sat,250/120V,7A,25W,20MHz	17c	Rhm	2SC4849
2SC5576	Si-N-Darl+Di	Pow,60±10V,4A,30W,80MHz,B>2000,int.Z-Diode (B→C)	17c	Rhm	2SD1595,2SD1796,2SD1987,2SD2131,+
2SC5577	Si-NPN	TV/Monitor-HD,Hi-def,1500/800V,15A,140W	77jS	Sanyo	BU2530AL,2SC3996,2SC5046

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2SC5578	Si-NPN	TV/Monitor-HD, 1600/800V, 15A, 140W	77j$	Sanyo	2SC5046
2SC558	Si-NPN	TV-HD, 250/80V, 5A, 50W	23a$	Toshiba	BU104, BU326A, BU606..608, 2SD916, 2SD1154
2SC5583	Si-NPN	TV/Monitor-HD, 1500/600V, 17A, 150W	77j$	Mat	2SC3997, 2SC4290A, 2SC4897, 2SD2356
2SC5584	Si-NPN	TV/Monitor-HD, 1500/600V, 20A, 150W	77j$	Mat	2SC3997, 2SC4290A, 2SC4897, 2SD2356
2SC5585	Si-NPN	AF-Dr/Out, 15V, 0,5A, 320MHz	35a(1,6mm)	Rhm	-
2SC5587	Si-NPN	TV/Monitor-HD, 1500/750V, 17A, 75W	18c	Tos	-
2SC5588	Si-NPN	TV/Monitor-HD, 1700/800V, 15A, 75W	18c	Tos	-
2SC5589	Si-NPN	TV/Monitor-HD, 1500/750V, 18A, 200W	77j$	Tos	2SC3997, 2SC4897
2SC559	Si-NPN	GenP, 60V, 0,3A, 0,6W, 230MHz	2a$	Tos	BC140..141, BC300..302, 2N3053..
2SC5590	Si-NPN	TV/Monitor-HD, 1700/800V, 16A, 200W	77j$	Tos	2SC4896
2SC5592	Si-NPN	Sw, Lo-sat, 15V, 2,5A, 180MHz, 30/110nS	35a	Matsushita	-
2SC56	Si-NPN	GenP, 20V, 25mA, 0,2W	?2a	Fui	BC168, BC183, BC238, BC548, 2SD767..
2SC560(N)	Si-NPN	GenP, 80V, 0,8A, 0,8W, 150MHz	2a$	Fui,Tos	BC140..141, 2N1990, 2N2102, 2N2405..
2SC5602	Si-NPN	npn RF fT 13.5GHz 6V 5mA	-	Nec	-
2SC5603	Si-NPN	npn RF fT 13.5GHz 6V 15mA	-	Nec	-
2SC5606	Si-NPN	VCO, Buffer-Amp, 2GHz, 2V, 5mA	35(1,6mm)	Nec	-
2SC5607	Si-NPN	Sw, Lo-sat, 15V, 5A, 0,55W, 380MHz, B>600, 30/221ns	40c	Sanyo	-
2SC561	Si-NPN	HF, 20V, 25mA, 0,2W, 200MHz	?7b	Fui	BF198..199, BF224..225, BF594..595,..
2SC5610	Si-NPN	Lo-sat, 60V, 7A, 18W, 330MHz, 30/315nS	17c	Sanyo	-
2SC5611	Si-NPN	Lo-sat, 60V, 5A, 10W, 100MHz, 100/600nS	14b	Sanyo	-
2SC5612	Si-NPN	TV/Monitor-HD, 2000/900V, 22A, 220W	77j$	Tos	-
2SC562(Z)	Si-NPN	HF/AF, AGC, 330MHz	5k	Mat	BF198..199, BF224..225, BF505..
2SC563(A,AZ)	Si-NPN	HF/AF, 40V, 25mA, 550MHz	5k	Mat	BF198..199, BF224..225, BF505..
2SC5637	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 10A, 85W	18c	Sanyo	BU2522AF, 2SC3897, 2SC4199A, 2SC5068
2SC5638	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 15A, 95W	18c	Sanyo	2SC4891, 2SC5045, 2SC5252
2SC5639	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 20A, 100W	18c	Sanyo	2SC5300, 2SC5516
2SC564	Si-NPN	Sw, 50V, 0,5A, 0,65W, -/85nS	2a$	Fui	BSS28..29, BSV77, 2N3724, 2SC1385..
2SC5646	Si-NPN	UHF/SHF LN, 9V, 30mA, >8GHz	35a(1,4mm)	Sanyo	-
2SC565	Si-NPN	Sw, 50V, 0,2A, 0,35W, -/125nS	2a$	Fui	BSV59, BSX48..49, 2N3903..3904..
2SC566	Si-NPN	VHF-A/Dr, 50V, 0,3A, 0,8W, 700MHz	5g	Nec	BFX55, 2SC2852
2SC5667	Si-NPN	VCO, Buffer-Amp, 2GHz, 2V, 5mA	35(1,6mm)	Nec	-
2SC5668	Si-NPN	VCO, Buffer-Amp, 2GHz, 2V, 5mA	35(1,6mm)	Nec	-
2SC5669	Si-NPN	AF, Sw-Pow, 250V, 15A, 140W, 10MHz	18j$	Sanyo	2SC3263, 2SC5358
2SC567	Si-NPN	VHF, LN, 30V, 0,02A, 1300MHz	5g	Nec	BF505, BF689, BF763, 2N2857..
2SC568	Si-NPN	VHF, LN, 30V, 0,02A, 900MHz	5g	Nec,Mic	BF505, BF689, BF763, 2N2857..
2SC5680	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 10A, 80W	18c	Sanyo	BU2522AF, 2SC3897, 2SC4199A, 2SC5068
2SC5681	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 15A, 85W	18c	Sanyo	2SC4891, 2SC5045, 2SC5252
2SC5682	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 20A, 95W	18c	Sanyo	2SC5300, 2SC5516
2SC5683	Si-NPN	TV/Monitor-HD, Hi-def, 1500/800V, 25A, 100W	18c	Sanyo	-
2SC569	Si-NPN	Min, Sw, 40V, 0,15A, 0,15W, <-/35nS	24b	old	(BSS11, BSX92..93, 2N2368..69(A),..)
2SC57	Si-NPN	HF-Dr/Out, 75V, 0,5A, 110MHz	2a$	Nec	(BD139, BD230, 2SD1200, 2SD1378,..)
2SC570	Si-NPN	=2SC569: 0,2A, 0,3W	8a	old	BSS11, BSX19..20, 2N2368..69(A)..
2SC571	Si-NPN	VHF-A/Dr/Out, 36V, 0,5A, Pq>1W(175MHz)	2a$	Mat	BFQ42, BFR98, BFS51, BLW16, BLY61
2SC572	Si-NPN	VHF-Pow, 36V, 1A, Pq>4W(175MHz)	49a*	Mat	(BLY55, BLY57)
2SC573	Si-NPN	VHF-Pow, 36V, 2A, Pq>12W(175MHz)	49a*	Mat	(BLY36, BLY79)
2SC574	Si-NPN	VHF-Dr/Out, 80V, 1A, 7,5W, 280MHz	49a	Mat	(BLY60)
2SC575	Si-NPN	VHF-Dr/Out, 80V, 1A, 5W, 210MHz	2a$	Mat	(BLY60)
2SC576	Si-NPN	Fast-Sw, 40V, 0,5A, 0,36W, <12/15nS	2a$	Mat	BSS10, BSX26, BSX39, 2N3261, 2SC4648
2SC577	Si-NPN	=2SC576: <12/18nS	2a$	Mat	BSS10, BSX26, BSX39, 2N3261, 2SC4648
2SC578	Si-NPN	Sw, 60V, 0,5A, 0,6W, <65/150nS	2a$	Nec	BSS13, BSV77, 2N5189, 2SC1385..1386,..
2SC579	Si-NPN	Sw, 30V, 0,2A, 0,36W, <75/50nS	2a$	Nec	BSS11..12, BSX19..20, 2N2368..69(A),..
2SC58(A)	Si-NPN	HF/Sw, 60..135V, 0,06A, 0,6W, 250MHz	2a$	Mat	BF257..259, BF657..659, 2N5058..59
2SC580	Si-NPN	GenP, 60V, 1A, 0,8W, 250MHz	2a$	Nec	BC140..141, 2N1990, 2N2102, 2N2405,..
2SC581	Si-NPN	HF, 30V, 0,03A, 0,14W, 230MHz	5g	Mat	BF240..241, BF254..255, BF594..595,..
2SC582	Si-NPN	Sw, Vid-Pow, 300V, 0,1A, 6,5W(Tc=70°)	22a$	Mat	2SC1505..1507, 2SC1755..1757, 2SC1819,..
2SC583	Si-NPN	UHF, 30V, 0,02A, 1300MHz	5g	Mat	BF377..378, BF689, BF763, 2N2857..
2SC584	Si-NPN	VHF-Pow, 80V, 2A, 200MHz	49a	Mat	BLY35, 2N3632
2SC585	Si-NPN	VHF-Pow, 65V, 3A, Pq>13,5W(175MHz)	49a	Mat	2N3632
2SC586	Si-NPN	Sw, Pow, 150V, 5A, 50W, 55MHz	23a$	Matsushita	BUW86..87, 2SC2837, 2SD731..732..
2SC587(M,N)	Si-NPN	GenP, 45V, 0,03A, 0,3W, 80MHz	2a$	Mat,Son,Tos	BC167, BC182, BC237, BC547, 2SC1890+
2SC587A(M,N)	Si-NPN	=2SC587: ra	2a$	-	BC169, BC184, BC239, BC549, 2SC2674+
2SC588	Si-NPN	GenP, 30V, 0,1A, 0,6W, 200MHz	2a$	Fui,Son	BC140..141, BC300..302, 2N2218..19..
2SC589(N)	Si-NPN	Vid, 165/165V, 0,08A, 0,75W, 200MHz	2a$	Mot,Son,Tos	BF257..259, BF657..659, 2N5058..59..
2SC59	Si-NPN	S/VHF/Vid, 120V, 0,3A, 0,8W, 150MHz	2a$	Nec	BC300, 2N1893(A), 2N2102, 2N2405..

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2SC590(N)	Si-NPN	GenP,120/70V,0,3A,0,8W,150MHz	2a$	Mit,Nec	BC300,2N1893(A),2N2102,2N2405..
2SC591(N)	Si-NPN	HF/Sw-Pow,100V,1,5A,20W,150MHz	2a$	Fui,Nec	(BD139,BD230,BD379,2SD1177..1178)
2SC592	Si-NPN	VHF-Pow,75V,2,5A,13W,180MHz	49a	Fui	BLY35,2N3632
2SC593	Si-NPN	HF,50V,0,03A,0,165W,230MHz	5g	Mat	BF240..241,BF254..255,BF594..595,..
2SC594(M,N)	Si-NPN	HF/Sw,60V,0,2A,0,75W,30/280nS	2a$	Fui,Mit,Nec	BSW51..52,BSY58,2N2218..19(A)..
2SC595(N)	Si-NPN	Sw,30V,0,1A,0,3W,450MHz,<100/100nS	2a$	Fui,Nec,Oki	BSV90..92,BSX92..93,2N2368..69(A),..
2SC596(N)	Si-NPN	VHF-A/Dr,60V,0,5A,0,8W,400MHz	5g	Fui,Nec	BFX55,BFS23,BLY34
2SC597(N)	Si-NPN	VHF-A/Dr/Out,65V,1A,400MHz	2a$	Fui,Mat,Tos	-
2SC598(N)	Si-NPN	VHF/UHF-Pow,65V,1,5A,Pq>3,5W(400MHz)	49a	Fui,Mat,Nec	-
2SC599(N)	Si-NPN	VHF-Pow,60V,1,5A,20W,>300MHz	55r	Mit	BLW23..24,BLY92..93
2SC60	Ge-NPN	GenP,20V,0,02A,0,1W	2a	Sanyo	AC127,ASY28..28
2SC600(N)	Si-NPN	VHF-Pow,65V,3A,Pq=15W(175MHz)	49a	Fui,Mat,Nec	BLY35,2N3632
2SC601(N)	Si-NPN	Fast-Sw,40V,0,1A,0,3W,580MHz,<12/18nS	2a$	Fui,Mat	BSV91..92,BSX92..93,2N2368..69(A),..
2SC602(N)	Si-NPN	UHF-A/Ocs,30V,0,03A,0,2W,800MHz	5g	Fui,Nec,Tos	BF377..378,BF689,BF763,2N2857..
2SC603	Si-NPN	Dual,Chopper,7V,0,05A,0,2W	84bf1	Nec	-
2SC604	Si-NPN	Min,GenP,45V,0,1A,0,15W	24b	Nec	(BC167,BC182,BC237,BC547,2SD767,..)
2SC605	Si-NPN	Min,30V,0,02A,VHF-M,480MHz	24b	Nec	(BF198..199,BF224..225,BF505,..)
2SC606	Si-NPN	Min,VHF-Pre,530MHz	24b	Nec	(BF225,BF310,BF314,BF505,..)
2SC607	Si-NPN	HF-Dr/Out,75V,0,6A,1W,70MHz	2a$	Hit	(BC140..141,BC300..302,2SC959,..)
2SC608(T)	Si-NPN	HF-Pow,75V,1,5A,Pq>1,2W(27MHz)	43a$	Hit	(BD139,BD230,BD379,2SD1177..1178)
2SC609(T)	Si-NPN	=2SC208:Pq>3W(27MHz)	43a$	Hit	(BD139,BD230,BD379,2SD1177..1178)
2SC61	Si-NPN	HF/Sw,30V,0,3A,1,2W,180MHz	2a$	Fui	(BD135,BD226,2SC3419)
2SC610	Si-NPN	HF/Sw-Pow,100V,10A,Pq=32W(40MHz)	38a$	Mat	-
2SC611(N)	Si-NPN	HF,20V,0,02A,1000MHz	5g	Fui,Mat,Nec	BF377..378,BF689,BF763,2N2857..
2SC612(N)	Si-NPN	HF,35V,0,02A,1300MHz	5g	Mat,Nec,Tos	BF377..378,BF689,BF763,2N2858..
2SC613	Si-NPN	Sw,40V,0,2A,0,36W,<25/25nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC614	Si-NPN	GenP,80V,1,5A,7,5W(Tc=25°),200MHz	2a$	Sanyo	BCX40,BSS15..16,BSX45..47,2SD854..
2SC615	Si-NPN	=2SC614:30V	2a$	Sanyo	BCX40,BSS15..16,BSX45..47,2SD854..
2SC616	Si-NPN	=2SC614:13W	2a$	Sanyo	(BD139,BD230,BD379,2SD1177..1178)
2SC617	Si-NPN	=2SC615:13W	2a$	Sanyo	(BD135,BD226,BD375,2SD1177..1178)
2SC618(A)	Si-NPN	VHF,LN,25V,20mA,600MHz	5g	Fui	BF225,BF310,BF314,BF502,BF505..
2SC619	Si-NPN	GenP,30V,0,2A,0,25W,250MHz	7b	Mit	BC183,BC548,BSV59,2N2221..22(A),..
2SC62	Si-NPN	Sw,40V,0,05A,0,36W,<19/75nS	2a$	Hit	BSS11,BSV91..92,BSX92..93,2N2368..
2SC620(M)	Si-NPN	=2SC619:50V	7b	Mit	BC182,BC547,BSV59,2N2221..22(A),..
2SC621(A,M)	Si-NPN	HF/Sw,25..30V,0,1A,0,15W,150MHz	4a	Mit	BC168,BC183,BC238,BC548,2SD767..
2SC622	Si-NPN	=2SC621:	4g	Mit	BC168,BC183,BC238,BC548,2SD767..
2SC623	Si-NPN	Min,Sw,40V,0,15A,0,15W,<-/90nS	24b	old	(BSS11,BSX92..93,2N2368..69(A),..)
2SC624	Si-NPN	=2SC623:0,2A,0,3W	8a	old	BSS11,BSX92..93,2N2368..69(A)..
2SC625	Si-NPN	-		old	-
2SC626	Si-NPN	HF-Ant/Dr/Out,50V,0,2A,0,75W,350MHz	2a$	Nec	BFW16..17,BFX55
2SC627(F)	Si-NPN	Vid,200V,0,1A,0,7W,20MHz	2a$	Fui	BF258..259,BF658..659,2N5058..59
2SC628	Si-NPN	VHF-Dr/Out,40V,0,5A,Pq=2W(200MHz)	2a$	Nec	BFW46,BLY33,BLX65,2N3924
2SC629	Si-NPN	UHF,18V,0,03A,800MHz	10b	Son	BF377..378,BF689K,BF763,2N2857..
2SC63	Si-NPN	Sw,25V,0,05A,0,3W,400MHz	2a$	Nec	BSY62..63,BSW41,2N706A,2N708..
2SC630	Si-NPN	-		Son	-
2SC631(A,S)	Si-NPN	=2SC632(A):ra,25V	10b	Son	BC169,BC184,BC239,BC549,2SC2675+
2SC632(A)	Si-NPN	GenP,50V,0,1..0,2A,140MHz	10b	Son	BC167,BC182,BC237,BC547,2SD767..
2SC633(A)	Si-NPN	GenP,25V,0,1..0,2A,140MHz	10b	Son	BC168,BC183,BC238,BC548,2SD767..
2SC634(A)	Si-NPN	=2SC633(A):50V	10b	Son	BC167,BC182,BC237,BC547,2SD767..
2SC635	Si-NPN	VHF-Pow,65V,1,5A,Pq>4W(175MHz)	49a	Nec	BLY60
2SC636	Si-NPN	VHF-Pow,65V,3A,Pq>7,5W(260MHz)	49a	Nec	BLY35,2N3632
2SC637	Si-NPN	VHF-Pow,40V,1A,Pq=6W(175MHz)	49a*	Nec	BLY57,2N3926
2SC638	Si-NPN	VHF-Pow,40V,2A,Pq=13,2W(175MHz)	49a*	Nec	BLY58,2N3927
2SC639	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<12/18nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC64	Si-NPN	HF/Vid,80V,0,05A,0,6W,100MHz	2a$	Sanyo	BF257..259,BF657..659,2N5058..59
2SC640	Si-NPN	Min,GenP,30V,0,1A,0,15W,100MHz	24b	Nec	(BC168,BC183,BC238,BC548,2SD767,..)
2SC641(H,K)	Si-NPN	HF/AF,Sw,40V,0,1A,400MHz,20/35nS	9b,7c	Hit	BFX59,BSV91..92,BSX92..93,2SC2851
2SC642	Si-NPN	TV-VD,1100/700V,1A,50W	23a$	Toshiba	..BU204..206,BU208A,2SC1922,2SD575,2SD818..
2SC642A	Si-NPN	=2SC642:1500/800V	23a$	-	BU204..206,2SC1922,2SD575,2SD818..
2SC643	Si-NPN	TV-HD,1100V,2,5A,50W	23a$	Toshiba	BU204..206,2SC1922,2SD575,2SD818..
2SC643A	Si-NPN	=2SC642:1500V	23a$	-	BU204..206,2SC1922,2SD575,2SD818..
2SC644	Si-NPN	GenP,LN,30V,0,05A,0,2SW,160MHz	7c	Mat,Mic	BC169,BC184,BC239,BC549,2SC2675+
2SC645(Z)	Si-NPN	HF,30V,0,03A,0,14W,200MHz	?2b	Mat	BF240..241,BF254..255,BF594..595,..
2SC646	Si-NPN	AF,Sw-Pow,60V,4A,25W,50MHz	23a$	Mat	2N3055,2SC2681,2SC2706,2SC2837,2SC3256

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2SC647	Si-NPN	AF,Sw-Pow,80V,5A,50W(Tc=70°),43MHz	23a$	Mat	2SC2681,2SC2706,2SC2837,2SC3256,BDW51C
2SC648(H)	Si-NPN	AF/HF,LN,30V,0,03A,0,1W,350MHz	2a$	Hit	BF198..199,BF224..225,BF505..
2SC649	Si-NPN	GenP,LN,30V,0,03A,0,2W,220MHz	2a	Hit	BC169,BC184,BC239,BC549,2SC2675+
2SC65(Y)	Si-NPN	=2SC64:150V,200MHz	2a$	Sanyo	BF257..259,BF657..659,2N5058..59
2SC650	Si-NPN	GenP,LN,30V,0,03A,0,2W,220MHz	2a	Hit	BC169,BC184,BC239,BC549,2SC2675+
2SC651	Si-NPN	VHF/UHF-A/Dr,45V,0,3A,Pq>0,75W(500MHz)	2a	Nec	BFS50,MRF515,2N3948,2SC2852..
2SC652(M)	Si-NPN	VHF/UHF-A/Dr,40V,0,3A,Pq>1W(500MHz)	2a	Nec	BFS50,MRF515,2N3948,2SC2852..
2SC653	Si-NPN	UHF,25V,0,02A,T400MHz	5g	Nec	BF377..378,BF689,BF763,2N2857..
2SC654	Si-NPN	VHF-A/Dr/Out,40V,0,3A,0,8W,650MHz	5g	Nec	BFR98,BFX55,MRF207,MRF225..
2SC655	Si-NPN	Min,AF/HF,10V,10mA,80MHz	4-SIP/o	Mat	-
2SC656	Si-NPN	Min,HF,10V,5mA,550MHz	4-SIP/o	Mat	-
2SC657	Si-NPN	VHF-Pre/Mix/Osc,18V,0,03A,500MHz	10b	Son	BF198..199,BF224..225,BF505..
2SC658(M)	Si-NPN	VHF-Pre/Mix/Osc,25V,0,02A,550MHz	4a	Mit	BF198..199,BF224..225,BF505..
2SC659	Si-NPN	=2SC658:400MHz	4a	Mit	BF198..199,BF224..225,BF505..
2SC66	Si-NPN	=2SC64:150V,130MHz	2a$	Sanyo	BF257..259,BF657..659,2N5058..59
2SC660	Si-NPN	VHF,AGC,25V,0,02A,600MHz	4g	Mit	BF225,BF310,BF314,BF502,BF505..
2SC661	Si-NPN	VHF,AGC,25V,0,02A,600MHz	4g	Mit	BF225,BF310,BF314,BF502,BF505..
2SC662	Si-NPN	UHF-Pre-in/Mix/Osc,25V,0,02A,800MHz	5g	Mit	BF377..378,BF689,BF763,2N2857..
2SC663	Si-NPN	UHF-Pre-in/Mix/Osc,25V,0,02A,900MHz	5g	Mit	BF377..378,BF689,BF763,2N2857..
2SC664	Si-NPN	AF,Sw-Pow,100V,5A,50W,15MHz	23a$	Hit	BD245C,BDV95,BDX95,BDW51C,2SC2681..
2SC665(H)	Si-NPN	=2SC664:125V	23a$	Hit	BD245D,2SC2706,2SC2837,2SD551..
2SC666	Si-NPN	=2SC664:150V	23a$	Hit	BD245D,2SC2837,2SD551,2SD1046..
2SC667	Si-NPN	HF,15V,0,03A,0,12W,600MHz	?7c	Sanyo	BF198..199,BF224..225,BF505..
2SC668	Si-NPN	=2SC667,ra	?7c	Sanyo	BF314,BFS02,BF505,BF507..
2SC668SP	Si-NPN	=2SC668:0,15W	41c	-	→2SC668
2SC669(A)	Si-NPN	AF,Sw,100V,3A,10W(Tc=25°),65MHz	2a$	Son	BSX64,2N4239,2SC2214
2SC67	Si-NPN	Sw,40V,0,2A,0,36W,400MHz,<20/40nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC670..673	Si-NPN	-		Son	-
2SC674	Si-NPN	VHF-Pre/Mix/Osc,600MHz	?7c	Sanyo	BF198,BF225,BF314,BF502,BF505..
2SC674SP	Si-NPN	=2SC674:0,15W	41c	-	→2SC674
2SC675	Si-NPN	Sw,Pow,250/120V,7A,50W,-/<3µS	23a$	NEC	BD550B,BU606..608,BUX18A..C,BUX80…
2SC676	Si-NPN	=2SC675:200/100V	23a$	Nec	BD245F,BU606..608,BUX18A..C,BUX80…
2SC677	Si-NPN	=2SC675:150/80V,-/<4,5µS	23a$	Nec	BD245D,BU606..608,BUX18A..C,BUX80…
2SC678	Si-NPN	=2SC675:100/60V,-/<4,5µS	23a$	Nec	BD245C,BU606..608,BUX18A..C,BUX80…
2SC679	Si-NPN	TV-VD,300V,2A,30W,20MHz	22a$	Hit	BU406..408,2SC779,2SC825,2SD1150..
2SC68(M)	Si-NPN	Sw,40V,0,2A,0,36W,400MHz,<20/40nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC680(A)	Si-NPN	TV-VD,200/120(A=140)V,2A,30W,20MHz	22a$	Hit	BU406..408,2SC779,2SC825,2SC1025..
2SC681	Si-NPN	TV-HD,200/70V,6A,50W	23a$	Hitachi	BU104,BU606..608,BUX80,2SD916
2SC681A,ARD	Si-NPN	=2SC681:250/80V	23a$	-	BU104,BU606..608,2SD916
2SC681AYL	Si-NPN	=2SC681:300/80V	23a$	-	BU104,BU606..608,2SD916
2SC682	Si-NPN	TV-IF-AGC,20V,0,02A,550MHz	5g	Hit	BF198,BF225,BF310,BF367,BF596..
2SC683	Si-NPN	VHF,AGC,20V,0,02A,550MHz	5g	Hit	BF198,BF225,BF310,BF367,BF596..
2SC684	Si-NPN	UHF-Osc,30V,0,05A,1100MHz	9b	Hitachi	BF377..378,BF689K,BF763,2N2857..
2SC685(A,H)	Si-NPN	AF/Vid-Out-Pow,300/300V,0,1A,4W,25MHz	22a$	Hit	2SC1505..1507,2SC1755..1757,2SC1905,..
2SC686	Si-NPN	Vid,150/150V,0,05A,0,8W,180MHz	2a$	Nec	BF257..259,BF657..659,2N5058..59
2SC687	Si-NPN	Sw,Pow,150V,5A,50W,-/<3µS	23a$	Matsushita	BD245D,BU606..608,2SD731..732..
2SC688	Si-NPN	VHF-Pow,60V,1,5A,20W,300MHz	55r	Mit	BLY97..98,2N5641
2SC689(H)	Si-NPN	Fast-Sw,40V,0,1A,0,3W,>600MHz,6,5/8nS	2a$	Hit	BSV91..92,BSX92..93,2N2368..69(A),..
2SC69	Si-NPN	HF/Sw,120V,0,3A,0,8W,160MHz	2a$	Nec	BC300,BSY55..56,2N1893(A)..
2SC690(A,M)	Si-NPN	VHF-Pow,60V,3(A=4)A,Pq=25W(150MHz)	55r	Mit	BLX39,MRF314A,MRF315A
2SC691(M)	Si-NPN	VHF-Dr/Out,60V,0,5A,Pq=3,5W(150MHz)	55r	Mit	BLY91
2SC692	Si-NPN	VHF-Pow,60V,1A,Pq=9W(150MHz)	55r	Mit	BLY92
2SC693(FP,NP)	Si-NPN	GenP,LN,40V,0,05A,0,1W,150MHz	?7c,7c	Say,Mic	BC184,BC413..414,BCS50,2SC2390..
2SC694(FP)	Si-NPN	GenP,LN,40V,0,05A,0,1W,100MHz	?7c,7c	Sanyo	BC184,BC413..414,BCS50,2SC2390..
2SC695	Si-NPN	AF,LN,20V,0,03A,0,1W,150MHz	24b	Nec	(BC169,BC184,BC239,BC549,2SC2390,..)
2SC696(Z)	Si-NPN	GenP,100V,3A,0,75W,100MHz	2a$	Mat	BSX64,2N4239,2SC2214
2SC696A	Si-NPN	=2SC696:130V	2a$	-	BU125S,BUX49..50,BUY41,2SD625
2SC697	Si-NPN	=2SC696:10W	43a$	Mat	(BD791,BDX35..37,MJE243..244)
2SC697A	Si-NPN	=2SC696:130V,10W	43a$	-	(BDV11,BDX36..37,2SD772)
2SC698	Si-NPN	AF/HF/Sw-Pow,100V,3A,10W,90MHz	43a$	Nec	(BD791,BDX35..37,MJE243..244)
2SC699	Si-NPN	HF-Out,50V,1A,10W,100MHz	43a$	Mit	(BD137,BD228,BD377,2SD1177..78..)
2SC70	Si-NPN	Vid,180V,0,02A,0,8W,130MHz	2a$	Tos	BF258..259,BF658..659,2N5058..59
2SC700	Si-NPN	VHF-A/Dr,60V,0,75A,300MHz	2a$	Mit	BFS23,BLY34
2SC701	Si-NPN	VHF-A/Dr,40V,0,75A,500MHz	2a$	Mit	BFS22,BFW46,BLY33,MRF237,2N3924

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2SC702	Si-NPN	VHF-Pow,40V,0,75A,Pq=3W(175MHz)	55r	Mit	BLY85,2N5589
2SC703	Si-NPN	VHF-Pow,40V,2A,Pq=12W(175MHz)	55r	Mit	BLW19,MRF208,MRF212,2N5590
2SC704	Si-NPN	VHF-Pow,40V,4A,Pq=17W(175MHz)	55r	Mit	BLY89,MRF209,2N5591,2N6082
2SC705	Si-NPN	VHF,15V,0,03A,700MHz	?7c	Sanyo	BF225,BF314,BF502,BF505,BF507..
2SC706	Si-NPN	=2SC705:800MHz	?7c	Sanyo	BF225,BF314,BF502,BF505,BF507..
2SC707(H)	Si-NPN	UHF,650MHz	5g	Hit	BF377..378,BF689,BF763,2N2857..
2SC708(H)	Si-NPN	GenP,60V,1A,0,75W,15MHz	2a$	Hit	BC140..141,2N1990,2N2102,2N2405..
2SC708A	Si-NPN	=2SC708:100V	2a$	-	BC141,2N1990,2N2102,2N2405..
2SC709	Si-NPN	GenP,25V,0,1A,0,2W,180MHz	7b	Mit	BC168,BC183,BC238,BC548,2SD767..
2SC71	Ge-NPN	Sw,18V,0,2A,0,15W	2a	Tos	AC127,ASY28..29,ASY73..75
2SC710	Si-NPN	GenP,AM/FM,30V,0,03A,0,2W,200MHz	7b	Mit	BC548,BF240..241,BF254..255..
2SC711	Si-NPN	GenP,30V,0,05A,0,2W,150MHz	7b	Mit	BC168,BC183,BC238,BC548,2SC1890+
2SC711A	Si-NPN	=2SC711:50V	7b	-	BC167,BC182,BC237,BC547,2SC1890+
2SC712(A)	Si-NPN	GenP,30V,0,1A,0,2W,150MHz	7b	Mit	BC168,BC183,BC238,BC548,2SC1890+
2SC713(M)	Si-NPN	Sw,30V,0,1A,0,2W,<60/150nS	7b	Mit	BSW41,BSY63,2N708,2N4123..24..
2SC714	Si-NPN	Sw,70V,0,2A,0,25W,<40/250nS	7b	Mit	BSW63..64,2N2221..22(A)
2SC715	Si-NPN	GenP,40V,0,1A,0,125W,140MHz	?7c	Mit,Say	BC167,BC183,BC237,BC547,2SC1815+
2SC716	Si-NPN	=2SC715:20V	?7c	Mit,Say	BC168,BC183,BC238,BC548,2SC1740+
2SC717	Si-NPN	VHF-Pre/Mix/Osc,>600MHz	9b	Hitachi	BF225,BF314,BF502,BF505,BF507..
2SC718	Si-NPN	Fast-Sw,20V,0,2A,0,3W,800MHz,-/15nS	2a$	Fui	BSS10..12,BSY17..18,2N2368..69(A),..
2SC719	Si-NPN	=2SC718:0,2W	2a$	Fui	BSS10..12,BSY17..18,2N2368..69(A),..
2SC72	Ge-NPN	Sw,18V,0,2A,0,15W	2a	Tos	AC127,ASY28..29,ASY73..75
2SC720	Si-NPN	TV-IF-AGC,25V,0,02A,500MHz	5g	Fui,Say	BF198,BF225,BF310,BF367,BF596..
2SC721	Si-NPN	=2SC720:	?2b	Fui,Say	BF198,BF225,BF310,BF367,BF596..
2SC722	Si-NPN	VHF/UHF,25V,25mA,700MHz	?2b	Fui,Say	BF377..378,BF689K,BF763,2N2857..
2SC723	Si-NPN	VHF/UHF,25V,25mA,500MHz	?2b	Fui,Say	BF377..378,BF689K,BF763,2N2857..
2SC724	Si-NPN	HF/Sw,30V,0,2A,0,2W,250MHz,-/<300nS	7c	Fui	BC168,BC183,BC238,BC548,2SC1815+
2SC725	Si-NPN	=2SC724:60V	7c	Fui	BC174,BC182,BC190,BC546,2SD767..
2SC726	Si-NPN	Fast-Sw,20V,0,2A,0,2W,800MHz,-/15nS	?2b	Fui,Say	BSS10..12,BSY17..18,2N2368..69(A),..
2SC727	Si-NPN	Nix,Vid,100/100V,0,1A,0,35W,20MHz	2a$	Fui	BF297..299,BSS38,BSX21,2SC3467..
2SC728	Si-NPN	=2SC727:200/200V	2a$	Fui	BF297..299,BF391..393,2SC3467..
2SC729	Si-NPN	GenP,50V,0,2A,0,6W,250MHz	2a$	Nec	BC140..141,BC300..302,2N3053..
2SC73	Ge-NPN	HF,15V,5mA,0,03W,20MHz	?2e	Son	-
2SC730	Si-NPN	VHF-A/Dr/Out,40V,0,4A,Pq=1,5W(150MHz)	2a	Mit	BFR98,BLW16,MRF225,MFR607..
2SC731(Z)	Si-NPN	UHF-A/Dr/Out,40V,0,5A,Pq=1,2W(500MHz)	2a	Mat	BFS50,MRF629,2N3948
2SC732(TM)	Si-NPN	GenP,LN,35..60V,0,1A,0,3W,80MHz	7c	Tos	BC550,2SC2240,2SC2459,2SC2674..75,..
2SC733	Si-NPN	GenP,35V,0,1A,0,3W,>80MHz	7c	Tos	BC168,BC183,BC238,BC548,2SD767..
2SC734	Si-NPN	GenP,70V,0,15A,0,3W,150MHz	7c	Tos	BC546,2SC1627,2SC2003
2SC735	Si-NPN	GenP,35V,0,4A,0,3W,300MHz	7c	Tos	BC337..338,BC635,BC637,2SC3377..
2SC736	Si-NPN	Sw,Pow,135V,5A,50W,<2/4µS	23a$	NEC	BD550,BU606..608,2SC2706,2SD1046,..
2SC737(M)	Si-NPN	VHF-Pow,60V,1,5A,Pq=14W(150MHz)	55r	Mit	BLW24,BLY92
2SC738	Si-NPN	VHF,25V,20mA,440MHz	7b	Mit	BF198..199,BF224..225,BF505..
2SC739	Si-NPN	=2SC738:350MHz	7b	Mit	BF198..199,BF224..225,BF505..
2SC74	Si-NPN	GenP,50V,0,1A,0,6W,300MHz	2a$	Tos	BC300..302,BSY58,2N3299..3300..
2SC740	Si-NPN	=2SC738:UHF,900MHz	4g	Mit	BF377..378,BF689,BF763,2N2857..
2SC741	Si-NPN	VHF-A/Dr/Out,40V,0,3A,Pq=0,3W(150MHz)	2a$	Mit	BFX55,2SC2852
2SC742	Si-NPN	VHF-Pow,69V,1,5A,12,5W,400MHz	49a	Fui	BLY35,BLY60,2N3632
2SC743	Si-NPN	VHF-Pow,65V,3A,25W,350MHz	49a	Fui	BLY35,2N3632
2SC744	Si-NPN	-		Fui	-
2SC745	Si-NPN	VHF-Pow,50V,1,5A,12,5W(450MHz)	49a	Fui	BLY35,BLY60,2N3632
2SC746	Si-NPN	VHF-Pow,45V,3A,25W,350MHz	49a	Fui	BLY35,2N3632
2SC748	Si-NPN	VHF-Pow,36V,1A,12,5W,400MHz	49a	Fui	BLY35,BLY60,2N3632
2SC749	Si-NPN	VHF-Pow,36V,2A,25W,350MHz	49a	Fui	BLY35,2N3632
2SC75	Ge-NPN	AM-IF,15V,5mA,10MHz	?2e	Son	-
2SC750	Si-NPN	-		Fui	-
2SC751	Si-NPN	VHF,20V,0,02A,650MHz	2a$	Tos	BF198..199,BF224..225,BF505..
2SC752(G,GTM)	Si-NPN	GenP,Sw,30V,0,1A,0,1W,300MHz	7c	Tos	BC168,BC183,BC238,BC548,2SD767..
2SC753	Si-NPN	UHF,1100MHz	24b	Nec	BF362..363
2SC754	Si-NPN	GenP,20V,0,15A,0,15W,90MHz	24b	Nec	(BC168,BC183,BC238,BC548,2SD767,..)
2SC755	Si-NPN	GenP,15V,0,1A,0,15W,100MHz	24b	Nec	(BC168,BC183,BC238,BC548,2SD767,..)
2SC756(A-..)	Si-NPN	AF,Sw,80..150V,4A,10W(Tc=25°),65MHz	2a$	Son	BUX34,BUY80,2SD625
2SC757	Si-NPN	UHF,1100MHz	24b	Nec	BF362..363
2SC758	Si-NPN	Sw,Pow,280/120V,8A,60W,18MHz	23a$	old	BD550B,BU606..608,BUX18A..C,BUX80...
2SC759	Si-NPN	=2SC758:180/100V	23a$	old	BD245E,BU606..608,BUX18A..C,BUX80...

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2SC76	Ge-NPN	AM-IF,15V,5mA,10MHz	?2e	Son	-
2SC760	Si-NPN	=2SC758:100/60V	23a$	old	BD245C,BU606..608,BUX18A..C,BUX80...
2SC761(Z)	Si-NPN	UHF,AGC,30V,0,02A,675MHz	5g	Mat	BF377..378,BF689,BF763,2N2857..
2SC762(Z)	Si-NPN	UHF,AGC,30V,0,02A,600MHz	5g	Mat	BF377..378,BF689,BF763,2N2857..
2SC763	Si-NPN	VHF,25V,20mA,>400MHz	7b	Mit	BF225,BF310,BF314,BFS02,BFS05..
2SC764	Si-NPN	Fast-Sw,40V,0,2A,0,36W,<12/18nS	2a$	Nec	BSS11,BSX19..20,2N2368..69(A)..
2SC765	Si-NPN	AM-Pow,60V,2A,Pq=20W(27MHz)	23a$	Mitsubishi	-
2SC766	Si-NPN	AM-Pow,120V,2A,Pq=19W(27MHz)	23a$	Mitsubishi	-
2SC767	Si-NPN	AM-Pow,180V,2A,Pq=19W(27MHz)	23a$	Mitsubishi	-
2SC768	Si-NPN	Sw,Pow,60/40V,10A,50W,-/<3µS	23a$	Mit	BD245A,BD311,BDV91,2N3055..
2SC769	Si-NPN	=2SC768:120/80V	23a$	Mit	BD245D,BDX51,BUV50,2N5633..34,2SD551..
2SC77	Ge-NPN	AM-IF,15V,5mA,10MHz	?2e	Son	-
2SC770	Si-NPN	=2SC768:200/100V	23a$	Mit	BD245F,BUV21,BUX17A..C,2SC3263,2SD555..
2SC771	Si-NPN	=2SC768:250/120V	23a$	Mit	BUV21,BUX17A..C,BUY18,2SC3263,2SD555..
2SC772	Si-NPN	AF,Sw,15V,0,03A,0,12W,300MHz	?7c	Sanyo	BF198..199,BF224..225,BF254..255,..
2SC773	Si-NPN	AM-Osc,50V,0,2A,Pq=40mW(27MHz)	7b	Mit	2SC2086,2SC2851,(BC237,BC546,..)
2SC774	Si-NPN	AM-Qsc/Dr,50V,0,5A,Pq=0,07W(27MHz)	2a$	Mit	MRF402,MRF8003,2SC781
2SC775	Si-NPN	AM-Dr/Out,75V,1A,Pq=0,7W(27MHz)	2a$	Mit	2SC781
2SC776	Si-NPN	AM-Dr/Out,75V,1A,Pq=1,5W(27MHz)	2a$	Mit	-
2SC777	Si-NPN	AM-Out,75V,1A,Pq=3,5W(27MHz)	43a$	Mit	(2SC1306,2SC1909,2SC2020,2SC2029,..)
2SC778	Si-NPN	AM-Out,80V,2A,Pq=4W(27MHz)	43a$	Mit	(2SC1306,2SC1909,2SC2020,2SC2029,..)
2SC779	Si-NPN	Sw,Pow,TV-HD,300/250V,2A,25W,8MHz	22a$	Tos	2SC825,(BU406..408,2SD1150,2SD1163,..)
2SC78	Ge-NPN	AM-Pre/Mix/Osc,15V,5mA,20MHz	?2e	Son	-
2SC780(G,GTM)	Si-NPN	Nix,Vid,70/70V,0,02A,100MHz	7c	Tos	BF297..299,BF422,BSW32,BSS38..
2SC780A(G,GTM)	Si-NPN	=2SC780:150/150V	7c	-	BF297..299,BF422,2SC2375,2SD2030,..
2SC781	Si-NPN	AM-Dr/Out,75V,1A,Pq=0,8W(27MHz)	2a$	Nec	BFS23,BLY34
2SC782(A)	Si-NPN	Sw,Pow,300/300V,1,5A,20(A=25)W,10MHz	22a$	Tos	2SC779,2SC825,(BUX84..85,2SD1150,..)
2SC783	Si-NPN	=2SC782:200/200V	22a$	Tos	2SC779,2SC825,(BU406..408,2SD1136,..)
2SC784	Si-NPN	FM-Preamp,40V,0,02A,500MHz	7c	Tos	BF241,BF255,BF314,BF495,BFS95..
2SC785	Si-NPN	FM-Mix/Osc,40V,0,02A,500MHz	7c	Tos	BF240,BF254,BF310,BF494,BFS95..
2SC786	Si-NPN	FM/VHF,20V,0,02A,>250MHz	5g	Tos	BF225,BF310,BF314,2SC1393..91..
2SC787	Si-NPN	UHF,25V,0,02A,1000MHz	5g	Tos	BF377..378,BF689K,BF763,2N2857..
2SC788	Si-NPN	Vid,250/150V,0,05A,0,8W,120MHz	2a$	Tos	BF258..259,BF658..659,2N5058..59
2SC789	Si-NPN	AF,Sw-Pow,70V,4A,30W,>3MHz	17j$	Tos,Mic	BD243A,BD537,BD539B,BD951,TIP31C...
2SC79	Si-NPN	VHF,15V,50mA,500MHz	2a$	Fui	BF198..199,BF224..225,BFS05..
2SC790	Si-NPN	AF,Sw-Pow,50V,3A,25W,>3MHz	17j$	Tos,Mic	BD241,BD243,BD535,BD935,TIP31A...
2SC791	Si-NPN	Sw,Pow,TV-VD,90/60V,1,5A,15W	22a$	Tos	BD239B,TIP31C,2SC779,2SC782..783,2SC825..
2SC792	Si-NPN	Sw,Pow,TV-SN,400/300V,1,5A,50W,10MHz	23a$	Toshiba	BU126,2SC1295,2SD1503
2SC793	Si-NPN	AF,Sw-Pow,100V,7A,60W,9MHz	23a$	Tos	BD245C,BDV95,BDX95,2N5632..33..
2SC794	Si-NPN	=2SC793:70V	23a$	Tos	BD245A,BDV93,BDX93,2N5874..
2SC795	Si-NPN	Vid-Pow,250/200V,0,1A,9W,180MHz	22a$	Son	2SC1505..1507,2SC1755..1757,2SC1905
2SC796	Si-NPN	AM/FM-Dr/Out,40V,0,5A,0,5W,230MHz	2a$	Fui	BFQ42,BFR98,BFS51,BLW16..
2SC797	Si-NPN	AM-Dr/Out,60V,0,5A,Pq=1,3W(27MHz)	2a$	Fui	-
2SC798	Si-NPN	AM-/Out,60V,1,5A,Pq=3,5W(27MHz)	2a$	Fui	-
2SC799	Si-NPN	AM-/Pow,80V,1,5A,Pq=3,5W(27MHz)	43a$	Nec	(2SC1306,2SC1909,2SC2020,2SC2029,..)
2SC80	Si-NPN	VHF-Pre/Mix/Osc,30V,80mA,200MHz	5g	Nec	BF198..199,BF224..225,BFS05..
2SC800	Si-NPN	VHF/UHF,30V,0,01A,800MHz	24b	Nec	BF362..363
2SC801	Si-NPN	AF/HF/Sw-Pow,75V,0,5A,13W,100MHz	2a$	Nec	(BD139,BD230,BD377,2SD1200,..)
2SC802	Si-NPN	AM-Dr/Out,Sw,60V,0,5A,Pq=1,3W(27MHz)	2a$	Fui	MRF229..230,MRF402
2SC803	Si-NPN	AM-Dr/Out,Sw,60V,1,5A,Pq=3,5W(27MHz)	2a$	Fui	-
2SC804	Si-NPN	VHF/UHF,15V,0,02A,1200MHz	24f	Son	BF362..363
2SC805	Si-NPN	GenP,Vid,100/100V,0,2A,0,75W,160MHz	2a$	Son	BF257..259,2SC3245(A),2SC3248..
2SC805A	Si-NPN	=2SC805:240/150V	2a$	-	BF258..259,BFR58..59,2SC3468
2SC806	Si-NPN	Sw,Pow,650V,10A,125W,5,5MHz	23a$	Son	BUS12(A),BUW26,BUW35..36,BUX80,..
2SC806A	Si-NPN	=2SC806:700/200V	23a$	-	BUS12(A),BUW26,BUW35..36,BUX80,..
2SC807	Si-NPN	Sw,Pow,500/220V,10A,125W,5,5MHz	23a$	Sony	BUW25,BUW34,BUW75,2SC3046..
2SC807A	Si-NPN	=2SC807:580/200V	23a$	-	BUW25,BUW34,BUW75,2SC3046..
2SC808	Si-NPN	Sw,Pow,300/100V,5A,80W,12MHz	23a$	Sony	BU606..608,BUW71,BUX16A..C..
2SC809	Si-NPN	UHF,25V,20mA,1200MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC81	Si-NPN	AF,Sw-Pow,50V,5A,125W	-	Mit	(BD245,BDV91,2SD895..896,2SD718,..)
2SC810	Si-NPN	VHF-A/Dr,40V,0,3A,0,5W,750MHz	5g	Fui	BFX55,2SC2852
2SC811	Si-NPN	VHF/UHF,35V,0,03A,800MHz	5g	Fui	BF377..378,BF689,BF763,2N2857..
2SC812(F)	Si-NPN	Fast-Sw,20V,0,1A,0,25W,<-/27nS	2a$	Fui	BSS11..12,BSX27,BSY17..18,2N2475..
2SC813	Si-NPN	-		Fui	-

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2SC814	Si-NPN	AF-Pow,30V,0,5A,0,4W,180MHz	7co	Nec	BC337..337,BC635,BC637,2SC3377..
2SC815(S)	Si-NPN	GenP,60V,0,2A,0,25W,200MHz	7c	Nec,Mic	BC174,BC182,BC190,BC546,2SC2675+
2SC816	Si-NPN	GenP,60V,1A,1W,140MHz	2a$	Mit	BC140..141,2N1990,2N2102,2N2405..
2SC817	Si-NPN	UHF,30V,0,02A,>550MHz	5g	Mit,Mic	BF377..378,BF689,BF763,2N2857..
2SC818	Si-NPN	Vid,160/120V,0,1A,0,8W,100MHz	2a$	Mit	BF257..259,2N5058..59,2SC3248..
2SC819	Si-NPN	VHF-Dr/Out,65V,1A,6W,500MHz	2a$	Hit	BFS23,BLY34
2SC82	Si-NPN	=2SC81:100V	-	Mit	(BD245C,BDV93,2SD718,2SD896..)
2SC820	Si-NPN	VHF-Pow,65V,1,5A,10W,500MHz	49a	Hit	BLY35,BLY60,2N3632
2SC821(Z)	Si-NPN	VHF-A/Dr,40V,0,3A,Pq>1W(175MHz)	2a	Mat	BFX55,MRF225,MRF607,2SC2852
2SC822(Z)	Si-NPN	VHF-A/Dr,40V,0,5A,Pq>1,7W(175MHz)	2a	Mat	BFS22,BFW46,BLY33,2N3924
2SC823	Si-NPN	VHF/UHF,LN,30V,0,06A,1500MHz	5g	Nec	BFR95,BFS50,MRF515
2SC824	Si-NPN	VHF/UHF,LN,50V,0,12A,1300MHz	5g	Nec	BFR95,2N3866,2N4428
2SC825	Si-NPN	Sw,Pow,TV-HD,300/300V,2A,30W,15MHz	22a$	Fui	2SC779,(BU406..408,2SD1150,2SD1163,..)
2SC826	Si-NPN	GenP,100V,0,3A,0,7W,20MHz	2a$	Fui	BC141,BC300,2N1889..90,2N1893(A),..
2SC827	Si-NPN	GenP,100V,0,5A,0,7W,20MHz	2a$	Fui	BC141,BC300,2N1889..90,2N1893(A),..
2SC828(Z)	Si-NPN	GenP,30V,0,05A,0,25W,220MHz	7c	Mat,Mic	BC168,BC183,BC238,BC548,2SC1890+
2SC828A(Z)	Si-NPN	=2SC828:45V	7c	-	BC167,BC182,BC237,BC547,2SC1890+
2SC829(Z)	Si-NPN	AM/FM-Pre/Mix/Osc,30V,30mA,230MHz	7c	Matsushita	BF240..241,BF254..255,BF594..595..
2SC83	Si-NPN	=2SC81:150V	-	Mit	(2SC2837,2SD731,2SD1046..1047,..)
2SC830	Si-NPN	AF,Sw-Pow,50V,3A,25W,20MHz	22a$	Hit	BD241,BD535,BD935,2N4231..33..
2SC830H	Si-NPN	=2SC830:100V,6MHz	22a$	-	BD241C,BD937,2N4233,2SD712..
2SC831	Si-NPN	VHF-Pow,50V,2A,Pq=12W(260MHz)	49a	Nec	BLY35,2N3632
2SC833(N)	Si-NPN	Sw,Pow,450/300V,2A,25W,>10MHz,<2/3µS	22a$	Fui,Hit,Say	BUW40,BUY63..64,2N4240,2N3585..
2SC836	Si-NPN	VHF,AGC,30V,0,02A,600MHz	7c	Nec	BF225,BF310,BF314,BFS02,BF505..
2SC837	Si-NPN	TV-IF,30V,0,02A,550MHz	7c	Nec	BF198..199,BF224..225,2SC2215..16,..
2SC838	Si-NPN	AM/FM-Pre/Mix/Osc,50V,0,05A,250MHz	7c	Nec,Mic	BF240..241,BF254..255,2SC2210..
2SC839	Si-NPN	=2SC838:ra	7c	Nec	BF241,BF255,BF495,BF595,2SC2210+
2SC84	Ge-NPN	Sw,25V,0,2A,0,12W,-/700nS	2a	Mit	ASY28..29,ASY73..75
2SC840	Si-NPN	AF,Sw-Pow,100/60V,2A,20W,50MHz	22a$	Mat	BD239C,BDY72,2N3441,2SC2528..2529..
2SC840A	Si-NPN	=2SC840:150/100V	22a$	-	BDY72,2N3441,2SC2529,2SD759..760..
2SC841(H)	Si-NPN	VHF-Dr/Out,36V,0,5A,450MHz	2a$	Fui,Hit	BFQ42,BFR98,BFS51,BLW16,BLY61
2SC842	Si-NPN	VHF-Pow,36V,1A,10W,450MHz	49a	Fui,Hit	BLY55,BLY57,BLY78,2N3926
2SC843	Si-NPN	VHF-Pow,36V,2A,20W,350MHz	49a	Fui,Hit	BLY36,BLY79
2SC844	Si-NPN	VHF-Dr/Out,40V,0,4A,Pq=1,1W(175MHz)	2a$	Fui	BFQ42,BFR98,BFS51,BLW16,BLY61
2SC845	Si-NPN	VHF-Dr/Out,55V,0,4A,Pq=1,4W(100MHz)	2a$	Fui	BFS23,BLY34
2SC846	Si-NPN	-		Nec	-
2SC847	Si-NPN	GenP,30V,0,2A,0,35W,70MHz	2a$	Fui	BC168,BC183,BC238,BC548,2SD767..
2SC848	Si-NPN	=2SC847:ra,60MHz	2a$	-	BC169,BC184,BC239,BC549,2SC2675+
2SC849	Si-NPN	Sw,30V,0,3A,0,35W,60MHz	2a$	Fui	BC337..338,2SC1627,2SC2002..03..
2SC85	Ge-NPN	Sw,25V,0,4A,0,12W,-/700nS	2a	Mit	ASY73..75
2SC850	Si-NPN	=2SC849:50V,0,5A,70MHz	2a$	Fui	BC337,2SC1627,2SC2002..03,2SC3377,..
2SC851	Si-NPN	AM/FM-Pow,50V,8A,Pq=40W(50MHz)	23a$	NEC	-
2SC852	Si-NPN	VHF/UHF,45V,0,08A,0,5W,1500MHz	5g	Nec	BFR36,BFW16,2SC2852
2SC853	Si-NPN	GenP,70V,0,2A,0,4W,100MHz	7co	Nec,Mic	BC639,2SC3665,2SD667,2SD1226..
2SC854	Si-NPN	VHF-Dr/Out,40V,0,3A,Pq=0,75W(175MHz)	2a$	Fui	BFR98,BFS51,BFX55,BLW16,BLY61
2SC855	Si-NPN	VHF-Dr/Out,40V,0,4A,Pq=0,9W(175MHz)	2a$	Fui	BFR98,BFS51,BFX55,BLW16,BLY61
2SC856	Si-NPN	Vid,150V,0,05A,0,3W,150MHz	2a	Hit	BF297..299,BF422A,2SC3467..68..
2SC857(H,K)	Si-NPN	Sw,Vid,200V,0,05A,0,2W,100MHz	2a	Hit	BF298..299,BF422A,2SC3467..68..
2SC858(FP)	Si-NPN	GenP,LN,20V,0,05A,0,1W,140MHz	7c	Say,Mic	BC169,BC184,BC239,BC549,2SC2675+
2SC859(FP)	Si-NPN	GenP,LN,20V,0,05A,0,1W,140MHz	7c	Samyo	BC169,BC184,BC239,BC549,2SC2675+
2SC86	Ge-NPN	Sw,25V,0,4A,0,12W,-/600nS	2a	Mit	ASY73..75
2SC860	Si-NPN	VHF/UHF,15V,0,03A,700MHz	5g	Sanyo	BF377..378,BF689,BF763,2N2857..
2SC861	Si-NPN	Sw,Pow,450/250V,1A,50W,7MHz	23a$	Hitachi	2SC1463,BU126,BU326A,BUW71,BUX45...
2SC862	Si-NPN	Sw,Pow,650/250V,5A,50W,7MHz	23a$	Hit	BU326(A),BU426(A),BUX48A,BUX97(A,B)...
2SC863	Si-NPN	VHF/IF,60V,25mA,600MHz	5k	Tos	BF198..199,BF224..225,BF310..311,..
2SC864	Si-NPN	VHF/IF,40V,25mA,600MHz	5k	Tos	BF198..199,BF224..225,BF310..311,..
2SC865	Si-NPN	AM-Pow,60V,2A,Pq=4,5W(50MHz)	2a$	Fui	-
2SC866	Si-NPN	AM-Pow,60V,1,5A,Pq=3,5W(27MHz)	43a$	Fui	(2SC1306,2SC1909,2SC2078,2SC2092,..)
2SC867	Si-NPN	Sw,Pow,400/150V,1A,23W,8MHz	22a$	Son	BUW40(A,B),TIP48,2SC1316,2SD860A,..
2SC867A	Si-NPN	=2SC867:520V,3A,48W	22a$	-	BUT93,TIP75C,2SC2826,2SC3038..
2SC868	Si-NPN	Sw,Vid,130/40V,0,03A,0,2W,150MHz	7b	Mit	BF297..299,BF422,2SC2375,2SC3467,+
2SC869	Si-NPN	=2SC868:160V	7b	-	BF297..299,BF422,BF483,2SC3467..
2SC87	Si-NPN	HF/Sw,30V,0,1A,0,6W,250MHz	2a$	Fui	BFW16..17,BFX55
2SC870	Si-NPN	GenP,LN,30V,0,03A,0,2W,150MHz	7b	Mit	BC169,BC184,BC239,BC549,2SC2675+

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2SC871	Si-NPN	GenP,LN,30V,0,03A,0,2W,150MHz	7b	-	BC169,BC184,BC239,BC549,2SC2675+
2SC872(M)	Si-NPN	UHF-Dr/Out,40V,0,4A,Pq=1,3W(400MHz)	2a$	Fui	BFS50,MRF629,2N3948,2SC2852
2SC873	Si-NPN	GenP,75V,1A,0,5W,200MHz	2a$	Sanyo	BC140..141,BSX45..47,2N1990..
2SC874	Si-NPN	=2SC873:50V	2a$	Sanyo	BC140..141,BSX45..47,2N1990..
2SC875	Si-NPN	GenP,75V,0,2A,0,5W,170MHz	2a$	Say,Mic	BC140..141,BC300..301,2N1711..
2SC876	Si-NPN	=2SC875:50V	2a$	Say,Mic	BC140..141,BC300..302,2N3053..
2SC877	Si-NPN	Sw,40V,0,2A,0,3W,<20/35nS	2a$	old	BSS11,BSX19..20,2N2368..69(A)..
2SC878	Si-NPN	=2SC877:<12/22nS	2a$	old	BSS11,BSX19..20,2N2368..69(A)..
2SC879	Si-NPN	Sw,60V,1A,0,8W,<70/100nS	2a$	old	BSS13,BSS27,BSV77,2N5189..
2SC88	Si-NPN	=2SC87:120V	2a$	-	BC300,BF257,BSY55..56,2N1893(A),..
2SC880	Si-NPN	Sw,60V,1A,0,8W	2a$	old	BSS13,BSS27,BSV77,2N5189..
2SC881	Si-NPN	AF-Pow,GenP,60V,0,2A,0,4W,150MHz	7co	Nec,Mic	BC337A,BC637,2SC3377,2SC3939..
2SC882	Si-NPN	Sw,Pow,150/100V,2A,25W,30MHz	23a$	old	-
2SC883	Si-NPN	Sw,Pow,90/70V,2A,25W,30MHz	23a$	old	-
2SC884	Si-NPN	AF,Sw-Pow,80V,2A,15W,30MHz	22a$	old	BDV10..12,2N4233,2SC3252
2SC885	Si-NPN	Sw,Pow,330/100V,7A,50W,-/<9µS	23a$	old	BU104,BU326A,BU606..608,BUX18(A..C)...
2SC886	Si-NPN	=2SC885:270/90V	23a$	old	BU104,BU326A,BU606..608,BUX18(A..C)...
2SC887	Si-NPN	=2SC885:210/80V	23a$	old	BU104,BU326A,BU606..608,BUX18(A..C)...
2SC888	Si-NPN	=2SC885:150/70V	23a$	old	BU104,BU606..608,BUW86..87..
2SC889	Si-NPN	=2SC885:90/60V	23a$	old	BU104,BU606..608,BUW86..87..
2SC89(H)	Ge-NPN	Sw,25V,0,4A,0,12W,-/380nS	2a	Hit	ASY73..75
2SC890	Si-NPN	UHF-Dr/Out,40V,0,4A,Pq=1,3W(500MHz)	2a	Nec	BFS50,MRF629,2N3948
2SC891	Si-NPN	UHF-Pow,40V,0,6A,Pq=4W(500MHz)	55s*	Nec	(BLW43,BLW80,2N5945)
2SC892	Si-NPN	UHF-Pow,40V,1,2A,Pq=8W(500MHz)	55s*	Nec	(BLU97,BLX68,BLY53)
2SC893	Si-NPN	AF/HF/Sw-Pow,100V,0,5A,12W,20MHz	43a$	Fui	(BD139,BD230,2SD1382,2SD1563)
2SC894	Si-NPN	GenP,25V,0,1A,0,1W,200MHz	10b	Son	BC168,BC183,BC238,BC548,2SD767
2SC895	Si-NPN	AF,Sw-Pow,150/90V,2,5A,23W,20MHz	22a$	Son	BD241D,2SD608(A),2SD772(A,B),2SD1138
2SC896	Si-NPN	GenP,55V,0,2A,0,3W,200MHz	2a	Nec	BC167,BC182,BC237,BC547,2SD767..
2SC897	Si-NPN	AF,Sw-Pow,150/90V,7A,60W,15MHz	23a$	Hit	BD245D,2N3442,2SD551,2SD732,2SD1046
2SC898	Si-NPN	=2SC897:150/110V,80W	23a$	Hit	BD245D,2N3442,2SD551,2SD732,2SD1046
2SC899	Si-NPN	GenP,LN,50V,0,05A,0,25W,250MHz	7c	Nec	BC184,BC414,BC550,2SC1775(A)..
2SC90(H)	Ge-NPN	Sw,25V,0,4A,0,12W,-/380nS	2a	Hit	ASY73..75
2SC900	Si-NPN	GenP,LN,30V,0,02A,0,25W,100MHz	7c	Nec,Mic	BC169,BC184,BC239,BC549,2SC2675+
2SC901	Si-NPN	Sw,Pow,TV-HD,200V,5A,50W,50MHz	23a$	Matsushita	2SD1154,BU104,BU326A,BU606..608
2SC901A	Si-NPN	=2SC901:250V	23a$	-	2SD1154,BU104,BU326A,BU606..608
2SC902	Si-NPN	Sw,Pow,150/80V,10A,75W,-/<4µS	23a$	Fujitsu	2SD551,2SD733,2SD1047,BU326A,BDW12...
2SC903	Si-NPN	GenP,35V,0,3A,0,2W,150MHz	7b	Mit	BC337,BC635,2SC3377,2SC3939..
2SC904	Si-NPN	=2SC903:50V	7b	Mit	BC637,2SD667,2SC3377,2SC3939..
2SC905	Si-NPN	=2SC903:65V	7b	Mit	BC637,2SD667,2SD1226,2SD1485..
2SC906	Si-NPN	GenP,50V,0,5A,0,6W,70MHz	2a$o	Ful	BC337,BC637,2SC3377,2SC3939..
2SC907(H)	Si-NPN	GenP,40V,0,1A,0,2W,240MHz	2a	Hit	BC167,BC183,BC237,BC547,2SD767..
2SC907A(AH)	Si-NPN	=2SC907:60(AH=70)V	2a	-	BC174,BC182,BC190,BC546,2SC3245+
2SC908	Si-NPN	UHF-Dr/Out,40V,0,5A,Pq=1,2W(500MHz)	2a	Mit	BFS50,MRF629,2N3948
2SC909	Si-NPN	UHF-Pow,40V,0,5A,Pq=3,5W(500MHz)	55r	Mit	BLW43,BLW80,2N5945
2SC91(H)	Ge-NPN	Sw,25V,0,4A,0,12W,-/360nS	2a	Hit	ASY73..75
2SC910	Si-NPN	UHF-Pow,40V,1A	55r	Mit	BLU97,BLX68,BLY53
2SC911(A)	Si-NPN	UHF-Dr/Out,40V,0,5A,Pq=1,4W(500MHz)	51r	Mit	BLX66
2SC912(M)	Si-NPN	GenP,Sw,30V,0,1A,0,15W,<25/140nS	4a	Mit	BSW41,BSY63,2N4123,2N2221..22..
2SC913	Si-NPN	Sw,40V,0,3A,0,3W,<45/42nS	2a$	Fui,Hit,Nec	BSS10,BSX19..20,BSX26,2N3261..
2SC914(A)	Si-NPN	=2SC913:<80/86nS	2a$	=2SC913	BSS10,BSX19..20,BSX26,2N3261..
2SC915(A)	Si-NPN	=2SC913:30V	2a$	=2SC913	BSS10,BSX19..20,BSX26,2N3261..
2SC916	Si-NPN	Sw,Pow,100/70V,1,5A,<63/160nS	2a$	Fui,Nec,Oki	(BD139,BD230,BD379,2SD1177..78,..)
2SC917	Si-NPN	TV-IF-Out,40V,0,05A,550MHz	5g	Hit	BF199,BF224,BF311,BF373,BF597..
2SC918	Si-NPN	VHF,20V,0,03A,400MHz	5g	Son	BF225,BF310,BF314,2SC1393..94..
2SC919	Si-NPN	-		Nec	-
2SC92	Si-NPN	FM/VHF-Pow,100V,2A,Pq=9W(100MHz)	2a$	Nec	-
2SC920	Si-NPN	AM/FM-Pre/Mix/Osc,50V,0,03A,250MHz	24b	Nec	BF240..241,BF254..255,BC594..595,..
2SC921	Si-NPN	FM-Preamp/Mix/Osc,25V,0,01A,650MHz	24b	Nec	BF225,BF310,BF314,2SC1393..94..
2SC922	Si-NPN	AM/FM,LN,30V,0,02A,>400MHz	7c	Nec,Mic	BF241,BF255,BF310,BF314,2SC829..
2SC923	Si-NPN	GenP,40V,0,1A,0,25W,100MHz	7c	Nec,Mic	BC167,BC183,BC237,BC547,2SC3112+
2SC924	Si-NPN	AF,AM-IF,30V,0,05A,0,25W,250MHz	7c	Nec	BF240..241,BF254..255,BF594..595,..
2SC925	Si-NPN	GenP,30V,0,05A,0,25W,250MHz	7c	Nec	BC168,BC183,BC238,BC548,2SC2390+
2SC926(A-4,A-5)	Si-NPN	Vid,115..210V,0,03..0,1A,0,1..0,25W	10b	Son	BF298..299,BF422,BF483,2SC3468..
2SC927	Si-NPN	VHF-LN,30V,0,02A,IF,500MHz	5g	Sanyo	BF225,BF310,BF314,BF502,2SC1856+

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2SC928	Si-NPN	VHF-LN,30V,0,02A,IF,500MHz	5g	Sanyo	BF225,BF310,BF314,BF502,2SC1856+
2SC929(NP,SPA)	Si-NPN	AF-LN,AM-V,15..30V,0,03A,300MHz	??c,7c	Say,Mic	BF240,BF254,BF494,BF594,2SC829..
2SC93	Si-NPN	=2SC92:80V	2a$	Nec	-
2SC930(NP,SP)	Si-NPN	FM,15..30V,0,03A,300MHz	??c,7c	Say,Mic	BF241,BF255,BF495,BF595,2SC829..
2SC931	Si-NPN	AF/HF/Sw-Pow,50V,3A,10W,120MHz	-	Sanyo	2SC3252,BD241A,BD785,BDX35,MJE240..242
2SC932	Si-NPN	=2SC931:30V	-	Sanyo	2SC3252,BD241A,BD785,BDX35,MJE240..242
2SC933	Si-NPN	GenP,Sw,50V,0,3A,0,2W,500MHz	5g	Say,Mic	BSV59,BSW41,BSY63,2N2221..22..
2SC933NP,SPA	Si-NPN	=2SC933:0,3W	7c	-	→2SC933
2SC934	Si-NPN	=2SC933:20V	5g	Say,Mic	BSV59,BSW41,BSY63,2N2221..22..
2SC934NP,SPA	Si-NPN	=2SC934:0,3W	7c	-	→2SC934
2SC935	Si-NPN	TV-Sw,Pow,300/300V,2,5A,50W,5MHz	23a$	Hitachi	2SD1154,BU104,BU126,BU606..608,BUX80
2SC936(A)	Si-NPN	TV-VD,1000/500(A=600)V,1A,22W,7MHz	23a$	Hitachi	BU204..206,2SC1101,2SC1167,2SD1095
2SC937	Si-NPN	TV-HD,1200/500V,2,5A,22W,4MHz	23a$	Hitachi	2SC1132,2SD1097..1098,BU204..206,BU208A…
2SC938	Si-NPN	GenP,60V,0,2A,0,25W,100MHz	7c	Nec,Mic	BC337A,BC637,2SC3939,2SD1226..
2SC939	Si-NPN	TV-HD,150V,5A,50W,20MHz	23a$	NEC	2SD916,BU104,BU326A,BU606..608…
2SC94	Si-NPN	=2SC92	2a$	Nec	-
2SC940	Si-NPN	=2SC939:200V,9A	23a$	Nec	BU106,BU109,BU124(A),BU326A
2SC941(TM)	Si-NPN	HF,35V,0,02A,0,2W,120MHz	7c	Tos	BF240..241,BF254..255,BF594..595,..
2SC942	Si-NPN-Darl	Dual,20V,0,02A,0,6W,700MHz	82	Fui	-
2SC943	Si-NPN	GenP,60V,0,2A,0,3W,220MHz	2a$	Nec	BC174,BC182,BC190,BC546,2N3904..
2SC944(S)	Si-NPN	GenP,60V,0,1A,0,25W,250MHz,20/300nS	7c	Nec	BC174,BC182,BC190,BC546,2N3904..
2SC945(T)	Si-NPN	GenP,60V,0,1A,0,25W,250MHz	7c	Nec,Mic	BC174,BC182,BC190,BC546,2SD767..
2SC945L	Si-NPN	=2SC945:ra	7c	-	2SC1775(A),2SC2674..75,2SC3378..
2SC946	Si-NPN	-		Nec	-
2SC947(Z)	Si-NPN	VHF/UHF,25V,15mA,650MHz	5g	Mat,Mic	BF377..378,BF689,BF763,2N2857..
2SC948(Z)	Si-NPN	VHF/UHF,25V,15mA,800MHz	5g	Mat,Mic	BF377..378,BF689,BF763,2N2857..
2SC949	Si-NPN	GenP,LN,45V,0,05A,0,2W,200MHz	7c	Njr	BC184,BC413..414,BC550,2SC2390..
2SC95	Si-NPN	Vid,140V,0,1A,0,8W,140MHz	2a$	Tos	BF257..259,BF657..659,2N5058..59
2SC950	Si-NPN	GenP,30V,0,1A,0,3W,100MHz	7c	Njr	BC168,BC183,BC238,BC548,2SD767..
2SC951	Si-NPN	=2SC950:60V	7c	Njr	BC174,BC182,BC190,BC546,2SD767..
2SC952	Si-NPN	=2SC950:100V	7c	Njr	2SC2240,2SC2459,2SC3245(A),2SC3248,..
2SC953	Si-NPN	GenP,30V,0,2A,0,6W,90MHz	8a	Njr	BC337..338,BC635,BC637,2SC3377..
2SC954	Si-NPN	GenP,60V,0,4A,0,6W,90MHz	8a	Njr	BC337A,BC637,2SC3939,2SD1226..
2SC955	Si-NPN	GenP,20V,0,05A,0,15W,150MHz	8a	Njr	BC168,BC183,BC238,BC548,2SC1890+
2SC956	Si-NPN	GenP,50V,0,05A,0,15W,200MHz	8a	Njr	BC167,BC182,BC237,BC547,2SC1890+
2SC957	Si-NPN	VHF,30V,0,1A,0,36W,700MHz	2a	Son	BF225,BF310,BF311,BF502,2SC1856..
2SC958	Si-NPN	-		Nec	-
2SC959(S)	Si-NPN	GenP,120V,0,7A,0,7W,100MHz	2a$	Nec,Mic	BC300,BSY55..56,2N1893(A),2N2102,..
2SC96	Si-NPN	Dual,25V,0,15A,0,5W,150MHz	81bt	Tos	(2N3409..3411,2N3728..3729)
2SC960(S)	Si-NPN	=2SC959:	43a$	Nec	(2SC2384,2SC2690(A),2SD1382)
2SC961	Si-NPN	AF,Sw-Pow,120/90V,7A,60W,13MHz	23a$	old	BD245C,BD550,2N5633,2SD1046..
2SC962	Si-NPN	=2SC961:100/80V	23a$	old	2NS632..33,BD245C,BDV95,BDW51C,BDX95…
2SC963	Si-NPN	GenP,35V,0,05A,0,25W,200MHz,B=70	2a	Fui	BC168,BC183,BC238,BC548,2SC1860+
2SC964	Si-NPN	=2SC963:B=100	2a	Fui	BC168,BC183,BC238,BC548,2SC1890
2SC965	Si-NPN	=2SC963:45V,-/<300nS	2a	Fui	BC167,BC182,BC237,BC547,2N3904..
2SC966	Si-NPN	GenP,30V,0,2A,0,5W,70MHz	2a	Fui	BC337..338,BC635,BC637,2SC3377..
2SC967	Si-NPN	GenP,30V,0,5A,0,5W,70MHz	2a	Fui	BC337..338,BC635,BC637,2SC3377..
2SC968	Si-NPN	GenP,50V,0,5A,0,5W,70MHz	2a	Fui	BC337,BC637,2SC3939,2SD1226..
2SC969	Si-NPN	GenP,50V,0,2A,0,5W,60MHz	2a	Fui	BC337,BC637,2SC3377,2SD1226..
2SC97	Si-NPN	Sw,60V,1A,0,8W,250MHz,<50/150nS	2a$	Nec	BSS13,BSV77,2N2218..19,2NS189..
2SC997	Si-NPN	HF/AF,40V,25mA,600MHz	5k	Tos	BF198..199,BF224..225,BF310..311,..
2SC998	Si-NPN	VHF-Dr/Out,40V,0,4A,Pq>1W(175MHz)	2a	Tos	BFQ42,BFS51,BFR98,BLW16,BLY61
2SC999	Si-NPN	TV-HD,1500/700V,1,5A,50W,1MHz	23a$	Toshiba	2SD575,2SD818,BU204..206,BU208A
2SC999A	Si-NPN	=2SC999:1500/650V,2,5A,4MHz	23a$	-	BU204..206,2SD575,2SD818
2SD100	Ge-NPN	AF-Driver,32V,0,4A,0,25W	2a	Tos	AC127,AC176,AC187,2SD72,2SD352
2SD1000	Si-NPN	GenP,60V,0,7A,110MHz	39b	Nec	BCX56,2SC2881,2SD100S..07,2SD1418,..
2SD1000-LK	Si-NPN	-	39	Nec	→2SD1000
2SD1000-LL	Si-NPN	-	39	Nec	→2SD1000
2SD1000-LM	Si-NPN	-	39	Nec	→2SD1000
2SD1001	Si-NPN	GenP,80V,0,3A,140MHz	39b	Nec	2SC2882,2SC3438,2SD875,2SD968(A)..
2SD1001-EK	Si-NPN	-	39	Nec	→2SD1001
2SD1001-EL	Si-NPN	-	39	Nec	→2SD1001
2SD1001-EM	Si-NPN	-	39	Nec	→2SD1001
2SD1002	Si-NPN	GenP,45V,1A,160MHz	39b	Nec	BCX54..56,2SC3444,2SD874A,2SD1368,..

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2SD1003	Si-NPN	=2SD1002: 60V	39b	Nec	BCX55..56, 2SC3444, 2SD874A, 2SD1368,..
2SD1004	Si-NPN	=2SD1002: 100V	39b	Nec	BCX56, 2SD1005, 2SD1368, 2SD1418..19,..
2SD1005	Si-NPN	100V, 1A, 100MHz	39b	Nec	BCX56, 2SC2881, 2SD1368, 2SD1418..19,..
2SD1005-BU	Si-NPN	-	39	Nec	→2SD1005
2SD1005-BV	Si-NPN	-	39	Nec	→2SD1005
2SD1005-BW	Si-NPN	-	39	Nec	→2SD1005
2SD1006	Si-NPN	100V, 0,7A, 90MHz	39b	Nec	BCX56, 2SC2881, 2SD1368, 2SD1418..19,..
2SD1006-HK	Si-NPN	-	39	Nec	→2SD1006
2SD1006-HL	Si-NPN	-	39	Nec	→2SD1006
2SD1006-HM	Si-NPN	-	39	Nec	→2SD1006
2SD1007	Si-NPN	=2SD1006: 120V	39b	Nec	2SC2881, 2SC4373, 2SD1418..19
2SD1007-HP	Si-NPN	-	39	Nec	→2SD1007
2SD1007-HQ	Si-NPN	-	39	Nec	→2SD1007
2SD1007-HR	Si-NPN	-	39	Nec	→2SD1007
2SD1008	Si-NPN	-		Tos	-
2SD1009	Si-NPN	GenP, LN, 150/150V, 0,05A, 160MHz	39b	Mat	-
2SD100A	Ge-NPN	=2SD100: 45V	2a	-	-
2SD101	Ge-NPN	AF-Driver, 80V, 0,6A, 0,25W	2a	Tos	-
2SD1010	Si-NPN	Hi-beta, Hi-Ueb, LN, 50V, 50mA, 0.3W, 200MHz	7c	Mat	2SC3495, 2SC3071, 2SD1424, 2SD2073
2SD1011	Si-NPN	Hi-beta, Hi-Ueb, LN, 100V, 0,02A, 200MHz	7c	-	2SC3495, 2SC3071, 2SD1511
2SD1012	Si-NPN	Lo-sat, 20V, 0,7A, 0,25W, 250MHz	40c	Sanyo	2SD1207, 2SD1616, 2SD1835
2SD1013	Si-NPN	-		Tos	-
2SD1014	Si-NPN	Sw, 50/50/50V, 2A, 0,9W, B>150	7c(9mm)	Son	-
2SD1015	Si-NPN	Sw, 140/50/50V, 2A, 0,9W, B>150	7c(9mm)	Son	-
2SD1016	Si-NPN	TV-HD, 1500/600V, 7A, 50W	23a$	Sanyo	BU2508A, 2SC3027..28, 2SC3686, 2SD822..
2SD1017	Si-NPN	TV-Reg, 250/250V, 2A, 50W	16j$	Nec	TIP51..55, 2SC2809
2SD1018	Si-NPN	250V, 4A, 80W, B>250	16j$	Nec	TIP51..54, 2SC2624, 2SC3083
2SD1019	Si-NPN	-		Nec	-
2SD102	Si-NPN	AF, Sw-Pow, 110/80V, 3A, 25W, 1MHz, 3/10µS	22a$	Tos	BD241C, BD243C, BDS39D, BD939..
2SD1020	Si-NPN	GenP, Lo-sat, 30V, 0,7A, 0,35W, 170MHz	40c	Nec	2SC4483, 2SC4485, 2SD1207, 2SD1616..
2SD1021	Si-NPN	GenP, 30V, 1A, 0,35W, 100MHz	40c	Nec	BC337..338, BC635, BC637, 2SD1225..
2SD1022	Si-NPN-Darl	Sw, Pow, 100/100V, 5A, 30W, B>1500	17j$	Shi	BD649, BD901, BDW23C, BDW63C..
2SD1023	Si-N-Darl+Di	Sw, Pow, 200/200V, 5A, 30W, B>1500	17j$	Shi	2SD930, 2SD1025
2SD1024	Si-NPN-Darl	Sw, Pow, 100/100V, 8A, 50W, B>1500	17j$	Shi	BD649, BD901, BDW73C, BDX53C..
2SD1025	Si-N-Darl+Di	Sw, Pow, 200/200V, 8A, 50W, B>1500	17j$	Shi	2SD1141, 2SD1756
2SD1026	Si-N-Darl+Di	Sw, Pow, 100/100V, 15A, 100W, B>1500	16j$	Shi	BDV67A, BDW83C, 2SD1296, 2SD1299..
2SD1027	Si-N-Darl+Di	Sw, Pow, 200/200V, 15A, 100W, B>1500	16j$	Shi	2SD1515
2SD1028	Si-NPN	-		Sanyo	-
2SD1029	Si-NPN	AF, Sw-Pow, 60V, 4A, 40W	17j$	Sanyo	BD243A, BD535, BD949, 2SC3179..
2SD1029K	Si-NPN	=2SD1029: 100V	17j$	-	BD243B, BD537, BD951, 2SD1528..
2SD103(M)	Si-NPN	=2SD102: 80/50V	22a$	Tos	BD241B, BD243B, BD539B, BD937..
2SD1030	Si-NPN	-	35	Mat	→2SD1030
2SD1030-R	Si-NPN	-	35	Mat	→2SD1030
2SD1030-S	Si-NPN	-	35	Mat	→2SD1030
2SD1030-T	Si-NPN	-	35	Mat	→2SD1030
2SD1031	Si-NPN-Darl	AF, Sw-Pow, 120V, 6A, 50W, B=4000	17j$	Sak	BD651, BDT21, BDW73D, BDX53D..
2SD1032	Si-NPN	AF, Sw-Pow, 60V, 4A, 60W, 0,2/1,4µS	18j$	Mat	BD245A, BDV91, 2SC2681, 2SD895..896,..
2SD1032A	Si-NPN	=2SD1032: 80V	18j$	-	BD245B, BDV93, 2SC2681, 2SD895..896,..
2SD1032B	Si-NPN	=2SD1032: 100V	18j$	-	BD245C, BDV95, 2SC2681, 2SD895..896,..
2SD1033	Si-NPN	Vid-Out, 200/150V, 2A, 20W, 10MHz	30j$	Nec	2SD1557, (2SD610, 2SD1138, 2SD1250(A))
2SD1034(A)	Si-NPN-Darl	Sw, Pow, 600/450V, 300A, 1250W, B=300	-	Tos	-
2SD1035	Si-NPN	Sw, Pow, 150/120/100V, 3A, 40W, 1,5MHz	17j$	Fui	-
2SD1036	Si-NPN	Sw, Pow, 150/120/100V, 15A, 150W, 1,5MHz	20j$	Fui	-
2SD1037	Si-NPN	Sw, Pow, 150/120/100V, 30A, 180W, 1,5MHz	20j$	Fui	-
2SD1038	Si-NPN	Sw, Pow, 150/120/100V, 40A, 180W, 1,5MHz	20j$	Fui	-
2SD1039	Si-NPN	=2SD1035:	22a$	Fui	-
2SD104	Ge-NPN	AF, 20V, 0,4A, 0,15W, B>60	2a	Tos	AC127, AC176, AC187, 2SD72, 2SD352
2SD1040(A)	Si-NPN	=2SD1036: 120W	23a$	Fui	-
2SD1041	Si-NPN	=2SD1037: 200W	23a$	Fui	-
2SD1042	Si-NPN	=2SD1038:	23a$	Fui	-
2SD1043	Si-N-Darl+Di	Sw, Pow, 430V, 5A, 80W, B=1000	23a$	Matsushita	BU322(A), BU921..922, 2SD1461..
2SD1044	Si-N-Darl+Di	Sw, Pow, 100V, 6A, 60W, B>700	18j$	Mat	TIP142, 2SD1170, 2SD1230
2SD1044A	Si-N-Darl+Di	=2SD1044: 170V	18j$	-	2SD921, 2SD1090, 2SD1122..1123
2SD1045	Si-NPN	GenP, 30V, 3A, 0,9W, 200MHz	7c(9mm)	Hit	2SD1347, 2SD1507, 2SD1617, 2SD1864

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2SD1046	Si-NPN	AF,Sw-Pow,150V,8A,80W,15MHz	18j$	Sanyo	BD245D,2SC2837,2SC3263,2SD751..
2SD1047	Si-NPN	AF,Sw-Pow,160V,12A,100W,15MHz	18j$	Sanyo	BD745F,2SC2987A,2SC3263
2SD1048	Si-NPN	20V,0.7A,0.25W,250MHz	35a	Sanyo	BCW65..66,2SC3265
2SD1048-X6	Si-NPN	-	35	Sanyo	→2SD1048
2SD1048-X7	Si-NPN	-	35	Sanyo	→2SD1048
2SD1048-X8	Si-NPN	-	35	Sanyo	→2SD1048
2SD1049	Si-NPN	AF,Sw,Pow,120V,25A,100W	18j$	Fjd	BD249C
2SD105	Ge-NPN	=2SD104:B>35	2a	Tos	AC127,AC176,AC187,2SD72,2SD352
2SD1050(K)	Si-N-Darl+Di	AF,Sw-Pow,100V,10A,80W,B>1000	20j$	Hit	2SD851..852,2SD1087,2SD1129
2SD1051	Si-NPN	GenP,50V,1,5A,1W,150MHz	9c	Mat	MPS650..651,2SC3328,2SD619,2SD1207..
2SD1052	Si-NPN	AF,Sw-Pow,Hi-beta,50V,3A,30W,B>250	17j$	Tos	2SC1983,2SD1943
2SD1052A	Si-NPN	=2SD1052:B>400	17j$	-	2SC1983,2SD1943
2SD1053	Si-NPN	Sw,Pow,400V,1A,15W	30j$	Nec	2SC3362..3363,2SC3632,(BD410)
2SD1054	Si-NPN	Sw,Pow,300/250V,3A,80W	23a$	Hitachi	BU126,TIPS1..54,2SC1463,2SD632
2SD1055	Si-NPN	GenP,40V,2A,0,75W,100MHz	9c	Rhm	MPS650,2SC3328,2SD1207,2SD1227..
2SD1056	Si-N-Darl+Di	Sw,Pow,600/600V,50A,400W,B>100	?74	Fjd	-
2SD1059	Si-NPN	AF,Sw-Pow,100V,6A,40W	17j$	Sanyo	BD243C,BD543C,BD801,2SD550..
2SD106	Si-NPN	-		Tos	-
2SD1060	Si-NPN	Lo-sat,60V,5A,30W,30MHz	17j$	Sanyo	2SC3253,2SC3258,2SD1236L
2SD1061	Si-NPN	Lo-sat,60V,7A,40W,10MHz	17j$	Sanyo	2SC3254,2SD1237L
2SD1062	Si-NPN	Lo-sat,60V,12A,40W,10MHz	17j$	Sanyo	2SC3345,2SD1212
2SD1063	Si-NPN	Lo-sat,60V,7A,60W,10MHz	18j$	Sanyo	2SD1187
2SD1064	Si-NPN	Lo-sat,60V,12A,80W,10MHz	18j$	Sanyo	2SC3256,2SD1238L
2SD1065	Si-NPN	Lo-sat,60V,15A,90W,10MHz	18j$	Sanyo	2SC3256,2SD1840
2SD1066	Si-NPN-Darl	Sw,Pow,600/600V,100A,770W,B>100	-	Fjd	-
2SD1067	Si-N-Darl+Di	Sw,Pow,600/600,30A,200W,B=200	?74	Fjd	-
2SD1068	Si-NPN	Sw,Pow,TV-HD,1000V,10mA,25W,8,5MHz	17j$	Son	2SC4256,2SC4451
2SD1069	Si-NPN+Diode	TV-HD,300/150V,7A,40W,18MHz	17j$	Tos	BU406D..408D,2SC3174,2SC3176
2SD107	Si-NPN-Darl	AF,Sw-Pow,80/60V,5A,50W,B>1000	23a$	Tos	BDX63A,MJ1001,2N6056,2SD1124..
2SD1070	Si-NPN	AF,Sw-Pow,100V,10A,60W	16j$	Nec	BD245C,BD545C,BDV95,2SC2681..
2SD1071	Si-N-Darl+Di	Sw-Reg,450/450V,6A,40W,B>500	17j$	Fjd	BU910..912,2SD798..99,2SD1245
2SD1072	Si-NPN-Darl	Sw-Reg,450/450V,5A,60W,B>500	17j$	Fjd	BU911..912,2SD978,2SD987,2SD1245..
2SD1073	Si-NPN-Darl	Sw,Pow,300/250V,4A,40W,B>1000	17j$	Fjd	BU910..912,2SD816,2SD978,2SD987..
2SD1074	Si-NPN	AF,Sw-Pow,120V,1A,10W,B=160	30j$	Hit	2SC2983,2SC4134,2SD1283..84,2SD1220..
2SD1075	Si-NPN	=2SD1074:B=100	30j$	Hit	2SC2983,2SC4134,2SD1283..84,2SD1220..
2SD1076(L,S)	Si-NPN	AF,Sw-Pow,25V,2,5A,20W	30j$	Hit	2SC3073,2SC3386,2SD1221,2SD1802..
2SD1077(L,S)	Si-NPN	=2SD1076:35V	30j$	Hit	2SC3073,2SC3386,2SD1221,2SD1802..
2SD1078(L,S)	Si-NPN	AF,Sw-Pow,50V,2A,20W	30j$	Hit	2SC3076,2SD1281..1282,2SD1801..
2SD1079(L,S)	Si-NPN	=2SD1078:80V	30j$	Hit	2SC3386,2SD1281..82,2SD1815..16
2SD108	Si-NPN-Darl	=2SD107:80/40V	23a$	Tos	BDX63A,MJ1001,2N6056,2SD1124..
2SD1080(L,S)	Si-NPN	AF,Sw-Pow,180/120V,1,5A,20W	30j$	Hit	2SC4027,2SD1033,2SD1557
2SD1081(L,S)	Si-NPN	=2SD1080:180/160V	30j$	Hit	2SC4027,2SD1033,2SD1557
2SD1082(L,S)	Si-NPN	=2SD1080:200/160V	30j$	Hit	2SD1033,2SD1557
2SD1083(L,S)	Si-NPN	AF,Sw-Pow,150V,2A,10W,B>150	30j$	Hit	2SD1033,2SD1557
2SD1084	Si-NPN-Darl	Sw,Pow,500/400V,50A,400W,B=300	?74	Hit	-
2SD1085(K)	Si-N-Darl+Di	Z-Di,300/300V,3A,40W,B=3000	17j$	Hit	2SD816,2SD1073,(BU806..807)
2SD1086	Si-NPN	-		Tos	-
2SD1087	Si-N-Darl+Di	AF,Sw-Pow,100V,15A,100W,B=3000	20j$	Tos	2SD829,2SD852,2SD1129..1130
2SD1088	Si-NPN-Darl	Sw,Pow,300/250V,6A,30W,B=5000	17j$	Tos	BU910..912,2SD835,2SD1114,2SD1307,..
2SD1089	Si-NPN-Darl	Sw,Pow,350/350V,6A,30W,B=1000	17j$	Tos	BU910..912,2SD835,2SD1114,2SD1307,..
2SD109	Si-NPN	-		Tos	-
2SD1090	Si-NPN	TV-Reg,Hi-beta,200V,5A,80W,B>500	18j$	Tos	-
2SD1091	Si-N-Darl+Di	AF,Sw-Pow,170V,4A,40W,B=5000	17j$	Mat	2SC3186,2SD930,2SD1023,2SD1121
2SD1092	Si-NPN	TV-Reg,Hi-beta,55V,4A,80W,B>500	18j$	Tos	2SC2825
2SD1093	Si-NPN	TV-SMPS,1000/400V,7A,50W,<5/11µS	23a$	Hitachi	BU536,BU546,BU902..903
2SD1094	Si-NPN	TV-SMPS,1000/400V,10A,50W,<5/21µS	23a$	Hitachi	BU626A
2SD1095	Si-NPN	TV-HD,1200V,1,5A,50W	23a$	Hitachi	BU204,2SD1097,2SC1132,2SC1167..
2SD1096	Si-NPN	AF,Sw-Pow,25V,1A,10W	30j$	Hit	2SD1078..79,2SD1295,2SD1801
2SD1097	Si-NPN	TV-HD,1200V,2,5A,50W	23a$	Hitachi	BU204,2SC1132,2SC1922,2SD818..
2SD1098	Si-NPN	TV-HD,1200V,3A,50W	23a$	Hitachi	BU207,2SC1875,2SD850,2SD1495..
2SD1099	Si-NPN	TV-HD,1200V,5A,50W	23a$	Hitachi	BU207,2SC2928,2SD954,2SD1496..
2SD11	Ge-NPN	Sw,25V,0,3A,0,15W,2,5MHz	2a$	Nec	ASY73..75
2SD110(M)	Si-NPN	AF,Sw-Pow,130V,10A,100W,1MHz,3/12µS	23a$	Tos	BDX11,2N3442,2SD551,2SD732..733..
2SD1100	Si-NPN	AF-Dr/Out,20V,2A,0,9W,B=400	7c(9mm)	Hit	2SC3225,2SC4389,2SD1014,2SD1146

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2SD1101	Si-NPN	GenP,25V,0,7A	35a	Hitachi	BCW65..66,2SC3265
2SD1101B	Si-NPN	-	35	Hit	→2SD1101B
2SD1101C	Si-NPN	-	35	Hit	→2SD1101C
2SD1102	Si-NPN	TV-HD,1200V,4A,50W	23a$	Hitachi	BU207,2SC1358,2SC3642,2SD1495..
2SD1103	Si-NPN	TV-HD,1200V,5A,50W	23a$	Hitachi	BU207,2SC2928,2SD954,2SD1496..
2SD1104	Si-NPN	TV-HD,1200V,6A,50W	23a$	Hitachi	BU508A,2SC3025,2SD821,2SD1497..
2SD1105	Si-NPN	AF,Sw-Pow,120V,15A,200W,1MHz	23a$	Mat	BDW10,2N5630..31,2SC1584,2SD752..
2SD1106	Si-NPN-Darl	Sw,Pow,450/450V,50A,400W,B=300	?74	Nec	-
2SD1107	Si-NPN-Darl	Sw,Pow,500/500V,50A,400W,B=300	?74	Nec	-
2SD1108	Si-NPN	-		Nec	-
2SD1109	Si-NPN	AF,Sw-Pow,100/100V,6A,70W	16j$	Nec	BD245C,BDV95,2SC2681,2SC2837..
2SD1109A	Si-NPN	=2SD1109:120/120V	16j$	-	BD245C,2SC2681,2SC2706,2SC2837..
2SD111(M)	Si-NPN	=2SD110:100V	23a$	Tos	BD317,BDW21C,BDY53,2N5632..33..
2SD1110	Si-NPN	AF,Sw-Pow,120/120V,7A,80W,15MHz	16j$	Nec	BD245C,2SC2681,2SC2706,2SC2837..
2SD1110A	Si-NPN	=2SD1110:130/130V	16j$	-	BD245D,2SC2706,2SD731,2SD1046..
2SD1111	Si-NPN-Darl	GenP,80V,0,7A,0,6,B=25000	7c	Sanyo	BC618,BC877,BC879,BSR51..52
2SD1112	Si-NPN	Sw,Pow,300/300V,0,2A,10W,70MHz	30j$	Mat	2SC3129,2SC3588,2SC3805,2SC4003..
2SD1113(K)	Si-N-Darl+Di	300/300V,6A,40W,B>500	17j$	Hit	2SD971,2SD991,2SD1071,2SD1088..89..
2SD1114(K)	Si-N-Darl+Di	Sw,Pow,400/300V,6A,50W,B>500	17j$	Hit	BU910..912,2SD835,2SD1245
2SD1115(K)	Si-N-Darl+Di	Sw,Pow,400/300V,3A,40W,B>500	17j$	Hit	2SD977..978,2SD987,2SD1072
2SD1116	Si-NPN-Darl	Sw,Pow,400/300V,3A,40W,B>500	17j$	Hit	2SD977..978,2SD987,2SD1072
2SD1117	Si-NPN	AF,Sw-Pow,40V,10A,50W	17j$	Fjd	BD705,BD743,BD805,BD905,2SD1062
2SD1117A	Si-NPN	=2SD1117:80V	17j$	-	BD709,BD743B,BD809,BD909..
2SD1118	Si-NPN-Darl	AF,Sw-Pow,80V,10A,50W,B>300,<1/5µS	17j$	Fjd	BDT63A,BDT65A,BDX33B,2SD2024..
2SD1119	Si-NPN	GenP,40V,3A,150MHz	39b	Mat	2SC4521,2SD1624,2SD2150
2SD1119-P	Si-NPN	-	39	Mat	→2SD1119
2SD1119-Q	Si-NPN	-	39	Mat	→2SD1119
2SD1119-R	Si-NPN	-	39	Mat	→2SD1119
2SD1120	Si-NPN-Darl	AF,Sw-Pow,200/150V,2A,40W,B=1000	17j$	Mat	2SC3186,2SD930,2SD1023,2SD1121
2SD1121	Si-NPN-Darl	AF,Sw-Pow,200/200V,3A,50W,B=1000	17j$	Mat	2SC3186,2SD930,2SD1023,2SD1025
2SD1122	Si-NPN-Darl	AF,Sw-Pow,200/150V,5A,80W,B=1000	18j$	Mat	2SD921,2SD1090,2SD1123
2SD1123	Si-NPN-Darl	AF,Sw-Pow,200/150A,100W,B=1000	18j$	Mat	-
2SD1124	Si-NPN-Darl	AF,Sw-Pow,80V,8A,80W,B=1000	18j$	Mat	BDV65A..C,TIP141..142
2SD1125	Si-NPN-Darl	AF,Sw-Pow,80V,12A,100W,B=1000	18j$	Mat	BDV65A..C,BDV67A..D,BDW83B..D..
2SD1126(K)	Si-N-Darl+Di	AF,Sw-Pow,120/120V,10A,50W,B>1000	17j$	Hit	BDT63C,BDT65C,BDX33D,2SD1607..
2SD1127(K)	Si-N-Darl+Di	AF,Sw-Pow,120V,10A,50W,B>1000	17j$	Hit	BDT63C,BDT65C,BDX33D,2SD1607..
2SD1128	Si-NPN-Darl	AF,Sw-Pow,150/100V,5A,30W,B=5000	17j$	Fjd	BDX53F,2SD830,2SD1169,2SD1500
2SD1129(K)	Si-NPN-Darl	AF,Sw-Pow,100V,15A,100W,B>1000	20j$	Hit	2SD829,2SD852,2SD1087
2SD113(M)	Si-NPN	AF,Sw-Pow,100V,30A,200W,1,5MHz,3/10µS	23a$	Tos	BDW30,BDY29,MJ802,2SD797
2SD1130(K)	Si-NPN-Darl	AF,Sw-Pow,100V,20A,100W,B>1000	20j$	Hit	-
2SD1131	Si-NPN	AF,Sw-Pow,50V,4A,40W,8MHz	17j$	Hit	BD243A,BD535,BD949,2SC3179..
2SD1132	Si-NPN	=2SD1131:60V	17j$	Hit	BD243A,BD535,BD949,2SC3179..
2SD1133	Si-NPN	AF,Sw-Pow,70/50V,4A,40W,7MHz	17j$	Hit	BD243A,BD537,BD951,2SC3179..
2SD1134	Si-NPN	=2SD1133:70/60V	17j$	Hit	BD243A,BD537,BD951,2SC3179..
2SD1135	Si-NPN	AF,Sw-Pow,100V,4A,40W,10MHz	17j$	Hit	BD243C,BD539C,BD953,2SD712..
2SD1136	Si-NPN	TV-HD,200/80V,4A,30W	17j$	Hit	BU406..408,2SD823,2SD1150,2SD1159,..
2SD1137	Si-NPN	TV-VD,100V,4A,40W	17j$	Hit	BD243C,BD539C,BD953,2SD712..
2SD1138	Si-NPN	AF,Sw-Pow,TV-VD,200/150V,2A,30W	17j$	Hit	BD239F,2SC2660,2SD610,2SD760
2SD1139	Si-NPN	AF,Sw-Pow,200/150V,2A,30W	17j$	Hit	BD239F,2SC2660,2SD610,2SD760
2SD114(M)	Si-NPN	=2SD113:70V	23a$	Tos	BDW30,BDY29,MJ802,2SD797
2SD1140	Si-NPN-Darl	GenP,30V,1,5A,0,9W,B=7000	7c(9mm)	Tos	2SD1536,2SD1786,2SD1861,2SD2046..
2SD1141(K)	Si-N-Darl+Di	Sw,Pow,400/300V,6A,40W,B=3000	17j$	Hit	BU910..912,2SD835,2SD1114,2SD1245
2SD1142	Si-NPN	TV-HD,1500V,3,5A,50W	23a$	NEC	BU208A,BU706,2SD849..850,2SD1495,..
2SD1143	Si-NPN	TV-HD,1500V,5A,50W	23a$	NEC	BU208A,BU706,2SC2928,2SD954..
2SD1144	Si-NPN	-		Nec	-
2SD1145	Si-NPN	Dr,Lo-sat,60V,5A,0,9W,120MHz	7c(9mm)	Sanyo	2SC4482,2SD2243
2SD1146	Si-NPN	AF-Dr/Out,50V,2A,0,9W,B=300	7c(9mm)	Son	2SC3328,2SC4145,2SD1207,2SD2182
2SD1147	Si-NPN-Darl	AF,Sw-Pow,120V,5A,30W,B=5000	17j$	Fjd	BD651,BDT21,BDW63D,BDW73D..
2SD1148	Si-NPN	AF-Out,140/140V,10A,100W	18j$	Tos	BD245D,2SC2706,2SC2987(A),2SD1047
2SD1149-R	Si-NPN	Hi-Ueb,Hi-beta,LN,100V,20mA,200MHz	35a	Mat	→2SD1149
2SD1149-S	Si-NPN	Hi-Ueb,Hi-beta,LN,100V,20mA,200MHz	35a	Mat	→2SD1149
2SD1149-T	Si-NPN	Hi-Ueb,Hi-beta,LN,100V,20mA,200MHz	35a	Mat	→2SD1149
2SD115	Si-NPN	-		Tos	-
2SD1150	Si-NPN	TV-HD,350/90V,6A,40W	17j$	Sanyo	BU406,BU408,2SC3175,2SC3591..

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2SD1151	Si-N-Darl+Di	TV-HD, 1500V, 5A, 95W, B=40..150	23a$	Matsushita	-
2SD1152	Si-NPN	GenP, 55V, 0,1A, 0,2W	7c	Hit	BC167, BC182, BC237, BC547, 2SD767..
2SD1153	Si-NPN-Darl	GenP, 80V, 1,5A, 0,9W, B>4000	7c(9mm)	Sanyo	2SD1579, 2SD1978, 2SD1981, 2SD2067
2SD1154	Si-NPN	TV-HD, 350/200V, 7A, 50W	23a$	Matsushita	BU104, BU606, BU608
2SD1155	Si-NPN-Darl	Sw, Pow, 400/400V, 50A, 300W, B=400	?74	Fjd	-
2SD1156	Si-NPN	Sw, Pow, 100/80V, 5A, 58W	49a$	Mit	2N5002, 2N5004, 2N5284..5285
2SD1157	Si-NPN	AF, Sw-Pow, Hi-beta, 80V, 4A, 25W, B=400	17j$	Fjd	2SC2315..16, 2SC2491
2SD1158	Si-NPN	AF, Sw-Pow, Hi-beta, 80V, 8A, 40W, B=400	17j$	Fjd	(2SC4024, 2SD1947)
2SD1159	Si-NPN	TV-HD, 200/60V, 4,5A, 40W, 10MHz	17j$	Sanyo	BU406..408, 2SC3189, 2SC3589, 2SD1163..
2SD116	Si-NPN	AF, Sw-Pow, 100/40V, 7A, 75W	23a$	Fui	BD245C, BDV95, BDX85, 2N5632..33..
2SD1160	Si-NPN+Diode	Sw, Pow, TV, R2=800Ω, Lo-sat, 50V, 2A, 10W	30j$	Tos	-
2SD1161-P4	Si-NPN	GenP, 30V, 0,03A, Emitter-R=130Ω,	35a	Sanyo	→2SD1161
2SD1161-P5	Si-NPN	GenP, 30V, 0,03A, Emitter-R=130Ω,	35a	Sanyo	→2SD1161
2SD1161-P6	Si-NPN	GenP, 30V, 0,03A, Emitter-R=130Ω,	35a	Sanyo	→2SD1161
2SD1162	Si-NPN-Darl	Sw, Pow, 500V, 5A, 40W, B>400, 1/18μS	17j$	Nec	BU912, 2SD798..799, 2SD987, 2SD1245
2SD1163	Si-NPN	TV-HD, 300/120V, 7A, 40W	17j$	Hit	BU406..408, 2SC3173, 2SC3590..
2SD1163A	Si-NPN	TV-HD, 350/150V, 7A, 40W	17j$	Hit	BU406..408, 2SC3175, 2SC3591..
2SD1164(Z)	Si-N-Darl+Di	AF, Sw-Pow, 150V, ±1,5A, 10W, B>2000	30j$	Nec	2SC4339, (2SD985..986)
2SD1165(A)	Si-NPN-Darl	Sw, Pow, 1000/900V, 100A, 1250W, B=150	-	Nec	-
2SD1166	Si-NPN-Darl	Sw, Pow, 1000/900V, 200A, 2500W, B=150	-	Tos	-
2SD1168	Si-NPN	Sw, Pow, TV-HD, 1500/800V, 5A, 50W	23a$	Matsushita	BU208A, BU706, 2SC2928, 2SD954..
2SD1169	Si-NPN-Darl	AF, Sw-Pow, 150/80V, 5A, 40W, B=10000	17j$	Mat	(2SD1128)
2SD117	Si-NPN	=2SD116: 150/80V	23a$	Fui	BD245D, BDX11, 2N3442, 2SD551, 2SD732,..
2SD1170	Si-NPN-Darl	AF, Sw-Pow, 120V, 6A, 70W, B=4000	18j$	Sak	2SD921, 2SD923, 2SD1090, 2SD1210..
2SD1171	Si-NPN+Diode	TV-HD, 1500V, 5A, 50W	23a$	Matsushita	BU208D, BU508D, 2SC3481..82, 2SC3681..
2SD1172	Si-NPN+Diode	TV-HD, 1500V, 5A, 65W	23a$	Matsushita	BU208D, BU508D, 2SC3481..82, 2SC3681..
2SD1173	Si-NPN+Diode	TV-HD, 1500V, 5A, 70W	23a$	Matsushita	BU508D, 2SC3481..82, 2SC3681, 2SD953,..
2SD1174	Si-NPN+Diode	TV-HD, 1500V, 5A, 95W	23a$	Matsushita	BU508D, 2SC3481..82, 2SC3681, 2SD953,..
2SD1175	Si-NPN+Diode	TV-HD, 1500V, 5A, 100W	23a$	Matsushita	BU508D, 2SD953, 2SC3481..82, 2SC3681,..
2SD1176	Si-N-Darl+Di	AF, Sw-Pow, 60V, 8A, 45W, B=4000	17j$	Mat	BD645, BD897, BDW73A, BDX53A..
2SD1176A	Si-N-Darl+Di	=2SD1176: 80V	17j$	-	BD647, BD899, BDW73B, BDX53B..
2SD1177	Si-NPN	AF-Pow, TV-VD, 100/60V, 2A, 20W, 230MHz	14h$	Hit	BD379, BD791, BDX35, MJE243..244
2SD1178	Si-NPN	=2SD1177: 100/80V	14h$	Hit	BD379, BD791, BDX35, MJE243..244
2SD1179	Si-NPN	AF, Sw-Pow, TV-VD, 120/100V, 1,5A, 20W	14h$	Hit	2SC2481, 2SC2690(A), 2SC3117, 2SD669..
2SD118	Si-NPN	AF, Sw-Pow, 130V, 7A, 100W, 2MHz	23a$	Tos	BD245D, BDX11, 2N3442, 2SD551, 2SD732,..
2SD1180	Si-NPN	=2SD1179: 120/110V	14h$	Hit	2SC2481, 2SC2690(A), 2SC3117, 2SD669..
2SD1181	Si-NPN	AF, Sw-Pow, 180V, 1,5A, 10W	17m$	Hit	(2SC2238A,B, 2SC2344, 2SD608A, 2SD1138+)
2SD1182	Si-NPN	=2SD1181: 50W	17m$	Hit	(2SC2660, 2SD760, 2SD772A,B,..)
2SD1183	Si-NPN	TV-SMPS, 1200/800V, 3A, 50W, <2/11μS	23a$	Hitachi	BU546, BU903, 2SC1875, 2SD1098..
2SD1184	Si-NPN	TV-SMPS, 1500/800V, 3A, 50W, <2/11μS	23a$	Hitachi	BU208A, BU706, BU908, 2SC3023..
2SD1185	Si-NPN	TV-SMPS, 1200/800V, 5A, 50W, <2/11μS	23a$	Hitachi	BU546, BU706, BU903, 2SD1099, 2SD1103
2SD1186	Si-NPN	TV-SMPS, 1200/800V, 5A, 50W, <2/11μS	23a$	Hitachi	BU208A, BU706, BU908, 2SC2928..
2SD1187	Si-NPN	AF, Sw-Pow, Lo-sat, 100/80V, 10A, 80W	18j$	Tos	2SD1064, 2SD1238L, 2SD1840
2SD1188	Si-NPN	-		-	-
2SD1189(F)	Si-NPN	AF-Pow, 40V, 2A, 5W, 100MHz	14b	Rhm	2SD1682..1683
2SD119	Si-NPN	=2SD118: 100V	23a$	Tos	BDW21C, BDX95, 2N3055, 2N5632..33..
2SD1190	Si-N-Darl+Di	AF, Sw-Pow, 70V, 4A, 30W, 20MHz, B=5000	17j$	Sanyo	BD717, BDW23B, BDW53B, BDW63B..
2SD1191	Si-N-Darl+Di	=2SD1190: 7A	17j$	Sanyo	BD647, BD899, BDW73B, BDX53B..
2SD1192	Si-N-Darl+Di	=2SD1190: 10A	17j$	Sanyo	BDT63A, BDT65A, BDW93B, BDX33B..
2SD1193	Si-N-Darl+Di	=2SD1190: 15A	18j$	Sanyo	BDV67A, BDW83B, 2SD1026
2SD1194	Si-N-Darl+Di	AF, Sw-Pow, 110V, 3A, 30W, 20MHz, B=4000	17j$	Sanyo	BDW53D, BDW63D, 2SD1091, 2SD1147..
2SD1195	Si-N-Darl+Di	=2SD1194: 5A	17j$	Sanyo	BD651, BDT21, BDW63D, 2SD1147..
2SD1196	Si-N-Darl+Di	=2SD1194: 8A	17j$	Sanyo	BD651, BDT21, BDW73D, BDX53D..
2SD1197	Si-N-Darl+Di	=2SD1194: 10A	18j$	Sanyo	BDV65C, BDV67B, BDW83D, 2SD1296..
2SD1198	Si-NPN-Darl	GenP, 30V, 1A, 1W, 150MHz, B>4000	9c	Mat	BC617..618, BC875, BSR50..52..
2SD1198A	Si-NPN-Darl	=2SD1198: 60V	9c	-	BC618, BC875, BSR50..52, 2SD893A..
2SD1199	Si-NPN	=2SD1010: 0,4W	9c	Mat	→2SD1010
2SD12	Si-NPN	AF, Sw-Pow, 75V, 2,5A, 60W	23a$	Mat	BD245B, BDV93, 2N4915, 2SD895..896..
2SD120(H)	Si-NPN	AF, Sw, 60V, 1,5A, 1W, 750/470nS	2a$	Hit	BCX40, BSX45..47, 2N5320..21..
2SD1200(F)	Si-NPN	AF, Sw-Pow, 80V, 0,7A, 5W, 120MHz	14b	Rhm	2SC3421, (BD139, BD230, 2SD1378,..)
2SD1201	Si-N-Darl+Di	Sw, Pow, 500/400V, 10A, 100W, B>200	23a$	Hitachi	BU323A, BU922, BUW81(A), 2SD685..
2SD1202	Si-NPN-Darl	Sw, Pow, 500/400V, 10A, 100W, B=100	23a$	Hitachi	BU323A, BU922, BUW81(A), 2SD685..
2SD1203	Si-N-Darl+Di	Sw, Pow, 500/400V, 15A, 100W, B>200	23a$	Hitachi	BU932, 2SD572..573, 2SD711(A)..
2SD1204	Si-NPN-Darl	Sw, Pow, 500/400V, 15A, 100W, B=100	23a$	Hitachi	BU932, 2SD572..573, 2SD711(A)..

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2SD1205	Si-NPN-Darl	=2SD892:	9c	Mat	→2SD892
2SD1205A	Si-NPN-Darl	=2SD892A:	9c	-	→2SD892A
2SD1206	Si-NPN	Hi-Ueb,30V,0,1A,0,4W,150MHz	9c	Mat	2SD889,2SD1807
2SD1207	Si-NPN	GenP,Lo-sat,60V,2A,1W,150MHz	7c(9mm)	Sanyo	2SC3328,2SC4145,2SD2069,2SD2485
2SD1208	Si-N-Darl+Di	45V,5A,100W,B=2k..20k	23a$	Toshiba	BDX63..MJ1000,TIP142,2SD629..
2SD1209	Si-NPN-Darl	GenP,60V,1A,0,9W,B>4000	7c(9mm)	Hit	2SD1153,2SD1660,2SD1809,2SD1981..
2SD121(H)	Si-NPN	=2SD120:100V	2a$	Hit	BCX40,BSS15,BSX46..47,2N5320..
2SD1210	Si-N-Darl+Di	AF,Sw-Pow,150V,±10A,80W,B>1000	16j$	Nec	BDV67D,2SD1123,2SD1296,2SD1299
2SD1211	Si-NPN	GenP,120V,0,5A,1W,200MHz	7c(9mm)	Mat	2SC223S,2SD667(A),2SD1812,2SD1937..
2SD1212	Si-NPN	Sw,Pow,Lo-sat,60V,12A,35W,120MHz	17j$	Sanyo	2SC3345..46,(2SD1062)
2SD1213	Si-NPN	Sw,Pow,Lo-sat,60V,20A,50W,120MHz	18j$	Sanyo	2SD1841
2SD1214	Si-N-Darl+Di	AF,Sw-Pow,25V,2A,35W,B=5000	17j$	Mat	BD713,BDT61,BDW53,2SD837..
2SD1215	Si-N-Darl+Di	AF,Sw-Pow,25V,4A,40W,B=5000	17j$	Mat	BD713,BDT61,BDW53,2SD837..
2SD1216	Si-N-Darl+Di	AF,Sw-Pow,25V,8A,45W,B=5000	17j$	Mat	BD643,BD895,BDW73,BDX53..
2SD1217	Si-N-Darl+Di	AF,Sw-Pow,50V,2A,35W,B=5000	17j$	Mat	BD715,BDT61,BDW53A,2SD837..
2SD1218	Si-N-Darl+Di	AF,Sw-Pow,50V,4A,40W,B=5000	17j$	Mat	BD715,BDT61,BDW53A,2SD837..
2SD1219	Si-N-Darl+Di	AF,Sw-Pow,50V,8A,45W,B=5000	17j$	Mat	BD645,BD897,BDW73A,BDX53A..
2SD122(H)	Si-NPN	AF,Sw-Pow,60/40V,3A,15W	2a$	Hit	(BD241A,BD535,BD935,2SD712,..)
2SD1220	Si-NPN	TV-AF-Pow,150V,1,5A,10W,100MHz	30j$	Tos	2SC4027,2SD1033,2SD1080..82,2SD1918..
2SD1221	Si-NPN	AF,Sw-Pow,60V,3A,20W,3MHz	30j$	Tos	2SC3386,2SC3518,2SC3592,2SD1802..
2SD1222	Si-N-Darl+Di	AF,Sw-Pow,60V,3A,15W,B=5000	30j$	Tos	2SD1520,2SD1817,2SD1955
2SD1223	Si-N-Darl+Di	AF,Sw-Pow,100V,4A,15W,B=5000	30j$	Tos	2SC4339,2SD1520,2SD1955
2SD1224	Si-NPN-Darl	AF,Sw-Pow,30V,1,5A,10W,B=10000	30j$	Tos	2SC3132,2SD1222,2SD1759,2SD1799..
2SD1225(M)	Si-NPN	AF-Dr/Out,40V,1A,1W,150MHz	9c	Rhm	BC63S,BC637,2SD667,2SD1225..
2SD1226(M)	Si-NPN	AF-Dr/Out,80V,0,7A,1W,120MHz	9c	Rhm	BC639,2SC2235,2SC2383,2SD667..
2SD1227(M)	Si-NPN	AF-Dr/Out,40V,2A,1W,100MHz	9c	Rhm	MPS650..651,2SC3328,2SD1146,2SD1207
2SD1228(M)	Si-NPN	AF-Dr/Out,50V,0,5A,0,6W,250MHz	9c	Rhm	BC337,BC635,BC637,2SC3377..
2SD1229	Si-N-Darl+Di	AF,Sw-Pow,70V,10A,60W,B=5000	18j$	Sanyo	BDV65A,BDW83B,TIP141,2SD1125..
2SD123(H)	Si-NPN	=2SD122:100/55V	2a$	Hit	(BD241C,BD539C,BD939,2SD712,..)
2SD1230	Si-N-Darl+Di	AF,Sw-Pow,110V,8A,60W,B=4000	18j$	Sanyo	BDV65C,2SD1210
2SD1231	Si-N-Darl+Di	AF,Sw-Pow,70V,10A,70W,B=5000	23a$	Sanyo	BDV65A,BDX83B,BDX85B,MJ3001..
2SD1232	Si-N-Darl+Di	AF,Sw-Pow,70V,15A,80W,B=5000	23a$	Sanyo	BDV67A,BDW83B,BDX67A,MJ4034..
2SD1233	Si-N-Darl+Di	AF,Sw-Pow,110V,8A,70W,B=4000	23a$	Sanyo	BDV65C,BDX63C,BDX65C,2SD922..
2SD1234	Si-N-Darl+Di	AF,Sw-Pow,110V,10A,80W,B=4000	23a$	Sanyo	BDV65C,BDW83D,BDX65C,2SD922..
2SD1235	Si-NPN	AF,Sw-Pow,Lo-sat,60V,8A,30W,120MHz	17j$	Sanyo	2SC3254..3255
2SD1236	Si-NPN	=2SD1236L:120V	17j$	Sanyo	2SC4329..30
2SD1236L	Si-NPN	AF,Sw-Pow,Lo-sat,90V,5A,30W,20MHz	17j$	Sanyo	2SC3258
2SD1237	Si-NPN	=2SD1237L:120V	17j$	Sanyo	2SC4329
2SD1237L	Si-NPN	AF,Sw-Pow,Lo-sat,90V,7A,40W	17j$	Sanyo	2SC4329
2SD1238	Si-NPN	=2SD1238L:120V	18j$	Sanyo	-
2SD1238L	Si-NPN	AF,Sw-Pow,Lo-sat,90V,12A,80W,20MHz	18j$	Sanyo	2SD1840
2SD1239	Si-NPN	AF,Sw-Pow,120V,20A,100W	23a$	Sanyo	BD249C,BD745D,2SD1049
2SD124(H)	Si-NPN	AF,Sw-Pow,60/40V,6A,60W,1,6/7,2µS	23a$	Hit	BD245A,BDV91,BDX91,2N5873..74..
2SD1240	Si-NPN	AF,Sw-Pow,120V,25A,120W	23a$	Sanyo	BD249C
2SD1241	Si-NPN	AF,Sw-Pow,60V,5A,60W	18j$	Mat	BD245A,BDV91,2SC2681,2SD895..896,..
2SD1241A	Si-NPN	=2SD1241:80V	18j$	-	BD245B,BDV93,2SC2681,2SD895..896,..
2SD1242	Si-NPN	AF,Sw-Pow,60V,6A,70W	18j$	Mat	BD245A,BDV91,2SC2681,2SD895..896,..
2SD1242A	Si-NPN	=2SD1242:80V	18j$	-	BD245B,BDV93,2SC2681,2SD895..896,..
2SD1243	Si-NPN	AF,Sw-Pow,60V,10A,100W	18j$	Mat	BD245A,BD545A,BDV91,2SC2681..
2SD1243A	Si-NPN	=2SD1243:80V	18j$	-	BD245B,BD545B,BDV93,2SC2681..
2SD1244	Si-NPN	=2SD965:1W	9c	Mat	→2SD965
2SD1245	Si-N-Darl+Di	Sw,Pow,500/400V,6A,40W,B>500	17j$	Mat	BU810,BU912,2SD798..799..
2SD1246	Si-NPN	AF-Dr/Out,Lo-sat,30V,2A,0,75W	7c	Sanyo	2SC4484,2SD1207,2SD2177
2SD1247	Si-NPN	=2SD1246:2,5A,1W	7c(9mm)	Sanyo	2SC4487,2SD1347
2SD1248	Si-N-Darl+Di	AF,Sw-Pow,120V,8A,40W,B>1000	17j$	Hit	BD651,BDT21,BDW73D,BDX53D..
2SD1249	Si-NPN	AF,Sw-Pow,350/250V,0,75A,35W,30MHz	30j$	Mat	(BUW40(A,B),TIP47..50,2SD859(A),..)
2SD1249A	Si-NPN	=2SD1249:400V	30j$	-	(BUW40(A,B),TIP48..50,2SD859A,..)
2SD124A(AH)	Si-NPN	=2SD124:75V,7A	23a$	-	BD245B,BDV93,BDX93,2N5874..
2SD125(H)	Si-NPN	AF,Sw-Pow,100/55V,6A,60W,1,6/7,7µS	23a$	Hit	BD245C,BDV95,BDX95,2N5632..33..
2SD1250(A)	Si-NPN	AF,Sw-Pow,200V,2A,30W,20MHz	30j$	Mat	(2SD1033,2SC2660,2SD760,2SD1138,..)
2SD1251	Si-NPN	AF,Sw-Pow,60V,4A,30W,1MHz	30j$	Mat	2SD1904,2SD1906,(BD241A,BD535,..)
2SD1251A	Si-NPN	=2SD1251:80V	30j$	-	2SD1906,2SD2200,(BD241B,BD537,..)
2SD1252	Si-NPN	AF,Sw-Pow,60V,3A,35W,30MHz	30j$	Mat	2SD1902,(BD241A,BD535,BD935,+)
2SD1252A	Si-NPN	=2SD1252:80V	30j$	-	2SD1906,2SD2200,(BD241B,BD537,..)

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2SD1253	Si-NPN	AF,Sw-Pow,60V,4A,40W,20MHz	30j$	Mat	2SD1904,2SD2198,(BD243A,BD535,..)
2SD1253A	Si-NPN	=2SD1253:80V	30j$	-	2SD1906,2SD2200,(BD243B,BD537,..)
2SD1254	Si-NPN	AF,Sw-Pow,Lo-sat,130V,3A,30W,30MHz	30j$	Mat	2SD1529
2SD1255	Si-NPN	AF,Sw-Pow,Lo-sat,130V,4A,35W,30MHz	30j$	Mat	-
2SD1256	Si-NPN	AF,Sw-Pow,Lo-sat,130V,5A,40W,30MHz	30j$	Mat	-
2SD1257	Si-NPN	AF,Sw-Pow,Lo-sat,130V,7A,40W,30MHz	30j$	Mat	-
2SD1257A	Si-NPN	=2SD1257:150V	30j$	-	-
2SD1258	Si-NPN	Hi-beta,200V,1A,40W,25MHz,B>500	30j$	Mat	-
2SD1259	Si-NPN	Hi-beta,80V,3A,40W,50MHz,B>500	30j$	Mat	-
2SD1259A	Si-NPN	=2SD1259:100V	30j$	-	-
2SD125A(AH)	Si-NPN	=2SD125:7A	23a$	-	BD245C,BDV95,BDX95,2N5632..33..
2SD126(H)	Si-NPN	AF,Sw-Pow,150/100V6A,60W,1,6/8,2µS	23a$	Hit	BD245D,BDX11,2N3442,2SD551,2SD732,..
2SD1260	Si-N-Darl+Di	AF,Sw-Pow,60V,2A,35W,20MHz,B>1000	30j$	Mat	(BD715,BDW23A,BDW53A,2SD837,..)
2SD1260A	Si-N-Darl+Di	=2SD1260:80V	30j$	-	(BD717,BDW23B,BDW53B,2SD837A,..)
2SD1261	Si-N-Darl+Di	AF,Sw-Pow,60V,4A,40W,20MHz,B>1000	30j$	Mat	(BD715,BDW23A,BDW53A,2SD837,..)
2SD1261A	Si-N-Darl+Di	=2SD1261:80V	30j$	-	(BD717,BDW23B,BDW53B,2SD837A,..)
2SD1262	Si-N-Darl+Di	AF,Sw-Pow,60V,8A,45W,20MHz,B>1000	30j$	Mat	(BD645,BD897,BDW73A,BDX53A,..)
2SD1262A	Si-N-Darl+Di	=2SD1262:80V	30j$	-	(BD647,BD899,BDW73B,BDX53B,..)
2SD1263	Si-NPN	AF,Sw-Pow,350/250V,0,75A,35W,30MHz	17c	Mat	2SC3969,(BUW40(A,B),TIP47..50)
2SD1263A	Si-NPN	=2SD1263:400/300V	17c	-	2SC3969,(BUW40(A,B),TIP48..50)
2SD1264(A)	Si-NPN	=2SD1250(A):	17c	Mat	2SC3298B,2SC4382,2SD1587,2SD2337
2SD1265(A)	Si-NPN	=2SD1251:	17c	Mat	BD951F,2SC3851,2SD1408,2SD2000
2SD1266(A)	Si-NPN	=2SD1252(A):	17c	Mat	BDT31F,2SC3851,2SD1408,2SD2000
2SD1267(A)	Si-NPN	=2SD1253(A):	17c	Mat	BD951F,2SC3851,2SD1408,2SD2000
2SD1268	Si-NPN	=2SD1254:	17c	Mat	-
2SD1269	Si-NPN	=2SD1255:	17c	Mat	-
2SD127	Ge-NPN	AF-Dr/Out,23V,0,5A,0,25W	2a	Son	AC127,AC176,AC187,2SD72,2SD352
2SD1270	Si-NPN	=2SD1256:	17c	Mat	-
2SD1271(A)	Si-NPN	=2SD1257(A):	17c	Mat	-
2SD1272	Si-NPN	=2SD1258:	17c	Mat	(2SC2317)
2SD1273	Si-NPN	=2SD1259:	17c	Mat	2SD1944,2SD2092,2SD2156,2SD2396..
2SD1273A	Si-NPN	=2SD1259A:	17c	-	2SD2092
2SD1274	Si-NPN	AF,Sw-Pow,150/80V,5A,40W,40MHz	17c	Mat	2SC3566,2SC4334
2SD1274A	Si-NPN	=2SD1274:200/80V	17c	-	2SC4153,(BD243F,2SD772A,B)
2SD1274B	Si-NPN	=2SD1274:250/80V	17c	-	(2SD772B)
2SD1275	Si-N-Darl+Di	=2SD1260:	17c	Mat	BDT61F,2SD1796,2SD1825,2SD1987..
2SD1275A	Si-N-Darl+Di	=2SD1260A:	17c	-	BDT61AF,2SD1414,2SD1788,2SD1933..
2SD1276	Si-N-Darl+Di	=2SD1261:	17c	Mat	BDT61F,2SD1796,2SD1825,2SD1987..
2SD1276A	Si-N-Darl+Di	=2SD1261A:	17c	-	BDT61AF,2SD1414,2SD1788,2SD1933..
2SD1277	Si-N-Darl+Di	=2SD1262:	17c	Mat	BD643F,BDT63F,2SD1416,2SD1826..27..
2SD1277A	Si-N-Darl+Di	=2SD1262A:	17c	-	BD645F,BDT63AF,2SD1415..16..
2SD1278	Si-NPN	Sw,Pow,1200/650V,8A,100W,<1/5µS	23a$	Mat	BU508A,2SC3412,2SD905..906,2SD1498..
2SD1279	Si-NPN	TV-HD,1400V,10A,50W,3MHz	23a$	Toshiba	2SC3688
2SD128	Ge-NPN	=2SD127:32V	2a	Son	AC127,AC176,AC187,2SD72,2SD352
2SD1280	Si-NPN	GenP,20V,1A,150MHz	39b	Mat	BC868,BCX54..56,BCX68,2SC2884..
2SD1280-Q	Si-NPN	-	39	Mat	→2SD1280
2SD1280-R	Si-NPN	-	39	Mat	→2SD1280
2SD1280-S	Si-NPN	-	39	Mat	→2SD1280
2SD1280-T	Si-NPN	-	39	Mat	→2SD1280
2SD1281	Si-NPN	AF,Sw-Pow,100V,2A,20W	30j$	Hit	2SC4135,2SD1557,2SD1815..16
2SD1282	Si-NPN	AF,Sw-Pow,100V,2A,20W	30j$	Hit	2SC4135,2SD1557,2SD1815..16
2SD1283	Si-NPN	AF,Sw-Pow,120V,2A,20W	30j$	Hit	2SC4135,2SD1557,2SD1815..16
2SD1284	Si-NPN	AF,Sw-Pow,120V,2A,20W	30j$	Hit	2SC4135,2SD1557,2SD1815..16
2SD1286(-Z)	Si-N-Darl+Di	AF,Sw-Pow,60V,±1A8W,B=2k..30k	30j$	Nec	2SC2871,2SD1598,2SD1800
2SD1287	Si-NPN-Darl	Sw,Pow,300/250V,30A,150W,B=300	23a$	Hitachi	BUT13,MJ10022..10023
2SD1288	Si-NPN	AF,Sw-Pow,120V,7A,70W,55MHz	16j$	Nec	BD245C,BD545D,2SD718,2SD1046..
2SD1289	Si-NPN	AF,Sw-Pow,120V,8A,80W,60MHz	16j$	Nec	BD245C,BD545D,2SD718,2SD1046..
2SD129	Si-NPN	AF,Sw-Pow,90/80V,3A,25W,1MHz	22a$	Tos	BD241B,BD939,2N4233,2SD712..
2SD1290	Si-NPN+Diode	TV-HD,1500V,3A,50W	18j$	Mat	BU706D,2SC3479,2SC3481,2SD1729..
2SD1291	Si-NPN+Diode	TV-HD,1500V,3A,50W	18j$	Mat	BU706D,2SC3479,2SC3481,2SD1729..
2SD1292	Si-NPN	AF-Dr/Out,120V,1A,0,9W,100MHz	7c(9mm)	Rhm	2SC2383,2SC3228,2SD667(A),2SD1812..
2SD1293(M)	Si-NPN	=2SD1292:1W	9c	Rhm	2SC2383,2SC3228,2N3700..01,2SD667
2SD1294	Si-N-Darl+Di	60V,5A,80W,B=2k..20k	18j$	Tos	BDV65,TIP140..142,2SD1124,2SD1170
2SD1295	Si-NPN	AF,Sw-Pow,50V,1,5A,20W,150MHz	30j$	Mat	2SC3076,2SD1078,2SD1281..1284..

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2SD1296	Si-N-Darl+Di	AF,Sw-Pow,150V,±15A,100W,B=1k..30k	16j$	Nec	BDV67D,2SD1027,2SD1299,2SD1515
2SD1297	Si-N-Darl+Di	AF,Sw-Pow,150V,25A,100W,B=1k..30k	16j$	Nec	-
2SD1298	Si-N-Darl+Di	Sw,Pow,500/400V,±10A,100W,B=200..2000	16j$	Nec	2SC3262,2SD979
2SD1299	Si-N-Darl+Di	AF,Sw-Pow,150V,15A,100W,B=5000	16j$	Nec	BDV67D,2SD1027,2SD1297,2SD1515
2SD13	Si-NPN	AF,Sw-Pow,35V,10A,100W	38a$	Mat	(BD245,BDV91,2SC2681)
2SD130	Si-NPN	=2SD129:60/50V	22a$	Tos	BD241A,BD535,BD935,2N4232..33..
2SD1300	Si-NPN	TV-HD,1500V,3A,50W	23a$	Hitachi	BU208A,2SC3023..24,2SD849..850..
2SD1301	Si-NPN+Diode	TV-HD,1500V,2A,45W	23a$	Matsushita	BU208D,BU705D,2SD993,2SD1728..
2SD1302	Si-NPN	Lo-sat,25V,0,5A,0,6W,200MHz	7c	Mat	-
2SD1303	Si-NPN	AF-Dr/Out,20V,1A,1W	7c(9mm)	Mat	2SC2236,2SD863,2SD1247,2SD1331..
2SD1304	Si-NPN+Diode	20V,0,1A,150MHz	35a	Matsushita	(BC846..848,BCW31..33,2SC1622..)
2SD1304-Q	Si-NPN	-	35	Mat	→2SD1304
2SD1304-R	Si-NPN	-	35	Mat	→2SD1304
2SD1304-S	Si-NPN	-	35	Mat	→2SD1304
2SD1305	Si-NPN	185/185V,0,15A,120MHz	35a	Mat	BFN24,BFN26,2SC3360,2SC4061
2SD1306	Si-NPN	GenP,30V,0,7A,250MHz	35a	Hitachi	BCW65..66,2SD1782
2SD1306-D	Si-NPN	-	35	Hit	→2SD1306
2SD1306-E	Si-NPN	-	35	Hit	→2SD1306
2SD1307	Si-NPN-Darl	Sw,Pow,350/300V,6A,35W,B=2500	17j$	Mat	BU910..912,2SD835,2SD1089,2SD1114,..
2SD1308	Si-N-Darl+Di	AF,Sw-Pow,100V,±5A,30W,B=2k..20k	15j$	Nec	BD901,BDW23C,BDW63C,2SD1147..
2SD1309	Si-N-Darl+Di	AF,Sw-Pow,150V,±8A,40W,B=2k..15k	15j$	Nec	BDX53F,2SD1025,2SD1500
2SD131	Si-NPN	AF,Sw-Pow,100V,5A,50W,20MHz	23a$	Tos	BD245C,BDV95,BDX95,2N5758..60..
2SD1310	Si-NPN	AF,Sw-Pow,60V,3A,30W,16MHz	15j$	Nec	BD241A,BD535,BD935,2SC3179..
2SD1311	Si-NPN	AF,Sw-Pow,100V,4A,40W,20MHz	15j$	Nec	BD241C,BD539C,BD937,2SD712..
2SD1312	Si-NPN	AF-Dr/Out,120V,1A,1W,120MHz	9b	NEC	2N3700..01,2SC2383,2SC3228,2SD667
2SD1313	Si-NPN	Sw,Pow,800/350V,25A,200W,0,8/3,5µS	77j$	Tos	2SC3989
2SD1314	Si-NPN-Darl	Sw,Pow,+Di(E→B),600/450V,15A,150W	77j$	Tos	-
2SD1315	Si-NPN-Darl	AF,Sw-Pow,150V,5A,40W,20MHz,B>5000	17c	Mat	2SD1590,(2SD1169)
2SD1316	Si-N-Darl+Di	30V,2A,35W,B>1000	30j$	Mat	(BD713,BDW23,BDW53,BDW63,..)
2SD1317	Si-N-Darl+Di	30V,4A,40W,B>1000	30j$	Mat	(BD713,BDW23,BDW53,BDW63,..)
2SD1318	Si-N-Darl+Di	30V,8A,45W,B>1000	30j$	Mat	(BD643,BD895,BDW73,BDX53,..)
2SD1319	Si-N-Darl+Di	60V,2A,35W,B>1000	30j$	Mat	(BD715,BDW23A,BDW53A,BDW63A,..)
2SD132	Si-NPN	AF,Sw-Pow,100V,20A,150W	68a$	Nec	2SD363,2SD372
2SD1320	Si-N-Darl+Di	60V,4A,40W,B>1000	30j$	Mat	(BD715,BDW23A,BDW53A,BDW63A,..)
2SD1321	Si-N-Darl+Di	60V,8A,45W,B>1000	30j$	Mat	(BD645,BD897,BDW73A,BDX53A,..)
2SD1322	Si-N-Darl+Di	=2SD1316:	17c	Mat	2SC3986,2SD1983,2SD1989,2SD2051..
2SD1323	Si-N-Darl+Di	=2SD1317:	17c	Mat	BDT61F,2SD1595,2SD1796,2SD2131..
2SD1324	Si-N-Darl+Di	=2SD1318:	17c	Mat	BD643F,2SD1416..17,2SD1826
2SD1325	Si-N-Darl+Di	=2SD1319:	17c	Mat	2SD1413,2SD1983,2SD2051
2SD1326	Si-N-Darl+Di	=2SD1320:	17c	Mat	BDT61F,2SD1595,2SD1796,2SD2131..
2SD1327	Si-N-Darl+Di	=2SD1321:	17c	Mat	BD643F,2SD1416..17,2SD1826
2SD1328	Si-NPN	GenP,25V,0,5A,200MHz,Ron=1Ω	35a	Matsushita	(BC817..818,BCX19..20,2SC3325,..)
2SD1328-R	Si-NPN	-	35	Mat	→2SD1328
2SD1328-S	Si-NPN	-	35	Mat	→2SD1328
2SD1328-T	Si-NPN	-	35	Mat	→2SD1328
2SD1329(K)	Si-N-Darl+Di	50V,6A,40W,B>2000	17j$	Hit	(BD645,BD897,BDW23A,BDW63A..)
2SD1330	Si-NPN	=2SD1302:	9c	Mat	→2SD1302
2SD1331	Si-NPN	AF-Dr/Out,40V,1,5A,0,9W	7c(9mm)	Hit	2SC4486,2SD1051,2SD1146,2SD1207..
2SD1332	Si-NPN	AF,Sw-Pow,100V,5A,60W,20MHz	18j$	Mat	BD245C,2SD718,2SD895..896,2SD731..
2SD1333	Si-NPN	AF,Sw-Pow,120V,6A,70W	18j$	Mat	BD245C,2SD718,2SD896,2SD731..
2SD1334	Si-NPN	AF,Sw-Pow,140V,7A,80W	18j$	Mat	BD245D,2SD1046..1047,2SD731..
2SD1335	Si-NPN	AF,Sw-Pow,150V,9A,100W	18j$	Mat	BD245D,2SC2987(A),2SC2838,2SD1047
2SD1336	Si-N-Darl+Di	AF,Sw-Pow,150/100V,6A,35W,B>1500	17c	Mat	2SD1590,(2SD1023,2SD1025,2SD1113,..)
2SD1336A	Si-N-Darl+Di	=2SD1336:180/120V	17c	-	2SD1792,(2SD991,2SD1088,2SD1113,..)
2SD1337	Si-NPN	TV-HD,1500/600V,2,5A,50W	23a$	Sanyo	BU205,BU705,2SC3023,2SD627..
2SD1338	Si-NPN+Diode	TV-HD,1500/600V,2,5A,50W	23a$	Sanyo	BU208D,BU705D,2SD993,2SD1728..
2SD1339	Si-NPN	TV-HD,1500/600V,3,5A,50W	23a$	Sanyo	BU208A,BU706,2SD849..850,2SD783..
2SD134	Ge-NPN	Sw,60V,5mA,0,03W	?2a	Son	-
2SD1340	Si-NPN+Diode	TV-HD,1500/600V,3,5A,50W	23a$	Sanyo	BU208D,BU706D,2SD993,2SD1729..
2SD1341	Si-NPN	TV-HD,1500/600V,5A,50W	23a$	Sanyo	BU208A,BU706,2SC2928,2SD954..
2SD1342	Si-NPN+Diode	TV-HD,1500/600V,5A,50W	23a$	Sanyo	BU208D,BU706D,2SD1171..75,2SD1730..
2SD1343	Si-NPN	TV-HD,1500/600V,6A,50W	23a$	Sanyo	BU508A,2SC3025,2SD821..822,2SD1497..
2SD1344	Si-NPN+Diode	TV-HD,1500/600V,6A,50W	23a$	Sanyo	BU508D,2SD903..904,2SD1731
2SD1345	Si-NPN	AF,Sw-Pow,60V,7A,40W,10MHz,0,2/1,2µS	17j$	Shi	BD243A,BD543A,BD797,2SC3254..

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2SD1346	Si-NPN	TV-HD, 1400V, 2,5A, 40W	17j$	Mat	BU505
2SD1347	Si-NPN	AF, Sw, Lo-sat, 60V, 3A, 1W, 150MHz	7c(9mm)	Sanyo	2SC4487, 2SC4482, 2SD1145
2SD1348	Si-NPN	=2SD1347: 4A, 10W	14h$	Sanyo	2SD1348
2SD1349	Si-NPN-Darl	Sw, Pow, 500V, 7A, 50W, 11MHz, B>150	17j$	Shi	BU810, 2SD1533
2SD1350	Si-NPN	Sw, 400/400V, 0,5A, 1W, 55MHz	9c	Mat	2SC4645, 2SC5018
2SD1350A	Si-NPN	=2SD1350: 600/500V	9c	-	-
2SD1351	Si-NPN	AF, Sw-Pow, 60V, 3A, 30W, 3MHz	17j$	-	BD241A, BD535, BD935, 2SC3179..
2SD1352	Si-NPN	AF, Sw-Pow, 80V, 4A, 30W, 8MHz	17j$	-	BD243B, BD537, BD951, 2SC3179..
2SD1353	Si-NPN	Sw, Pow, Hi-beta, 50V, 3A, 30W, 5MHz, B=600	?15j$	Tos	2SD1052, 2SC1983, 2SD1943, 2SD1157
2SD1354	Si-NPN	AF, Sw-Pow, 60V, 3A, 30W, 3MHz	?15j$	Tos	BD241A, BD535, BD935, 2SC3179..
2SD1355	Si-NPN	AF, Sw-Pow, 100V, 5A, 40W, 12MHz	?15j$	Tos	BD243C, BD539C, BD953, 2SD613..
2SD1356	Si-NPN	AF, Sw-Pow, 80V, 4A, 30W, 8MHz	?15j$	Tos	BD243B, BD539B, BD951, 2SC3179..
2SD1357	Si-N-Darl+Di	AF, Sw-Pow, 100V, 7A, 40W, B=6000	?15j$	Tos	BD649, BD901, BDW73C, BDX53C..
2SD1358	Si-N-Darl+Di	AF, Sw-Pow, 80V, 7A, 40W, B=6000	?15j$	Tos	BD647, BD899, BDW73B, BDX53B..
2SD1359	Si-N-Darl+Di	AF, Sw-Pow, 60V, 7A, 40W, B=6000	?15j$	Tos	BD645, BD897, BDW73A, BDX53A..
2SD136	Si-NPN	Vid-Pow, 200/200V, 0,1A, 4W, 20MHz	?22	Fui	(BF415, BF458..459, 2SC3502..03,..)
2SD1360	Si-N-Darl+Di	Sw, Pow, 600/400V, 6A, 30W, B=1000	?15j$	Tos	BU810, 2SC3579, 2SD798..799
2SD1361	Si-NPN-Darl	Sw, Pow, 300/250V, 6A, 30W, B=5000	?15j$	Tos	BU910..912, 2SD1088..89, 2SD1113..14,..
2SD1362	Si-NPN	Lo-sat, 100V, 7A, 40W, 10MHz	?15j$	Tos	2SD1237L
2SD1363	Si-NPN	Lo-sat, 70V, 7A, 40W, 10MHz	?15j$	Tos	2SC3254, 2SD1237L
2SD1364	Si-NPN+Diode	TV-HD, 300/150V, 7A, 40W	?15j$	Tos	BU406D..408D, 2SC3174, 2SC3176
2SD1365	Si-NPN	Sw, Pow, 800/400V, 3A, 40W, <1/8µS	?15j$	Tos	BUT11(A), BUV46(A), 2SC3086, 2SC3490..
2SD1366	Si-NPN	AF, 25V, 1A, 240MHz	39b	Hit	BC868, BCX54..56, BCX68, 2SC3444..
2SD1366A	Si-NPN	=2SD1366: 30V	39b	-	BCX54..56, 2SC2873, 2SC3444, 2SD874A,..
2SD1366-AA	Si-NPN	-	39	Hit	→2SD1366
2SD1366A-AC	Si-NPN	-	39	Hit	→2SD1366A
2SD1366A-AD	Si-NPN	-	39	Hit	→2SD1366A
2SD1366-AB	Si-NPN	-	39	Hit	→2SD1366
2SD1367	Si-NPN	AF, 20V, 2A, 100MHz	39b	Hit	2SC2883, 2SC3443, 2SC3439, 2SC2982
2SD1367-BA	Si-NPN	-	39	Hit	→2SD1367
2SD1367-BB	Si-NPN	-	39	Hit	→2SD1367
2SD1367-BC	Si-NPN	-	39	Hit	→2SD1367
2SD1368	Si-NPN	AF, 100V, 1A, 100MHz	39b	Hit	BCX56, 2SD1005, 2SD1368, 2SD1418..1419
2SD1368-CA	Si-NPN	-	39	Hit	→2SD1368
2SD1368-CB	Si-NPN	-	39	Hit	→2SD1368
2SD1368-CC	Si-NPN	-	39	Hit	→2SD1368
2SD1369	Si-N-Darl+Di	AF, Sw-Pow, 60V, 3A, 25W, B=5000	?15j$	Tos	BD715, BDW23A, BDW53A, BDW63A..
2SD137	Si-NPN	=2SD136: 300/300V	?22	Fui	(BF417, BF459, 2SC3417, 2SC3503,..)
2SD1370	Si-N-Darl+Di	AF, Sw-Pow, 100V, 4A, 30W, B=4000	?15j$	Tos	BDW23C, BDW53C, BDW63C, 2SD837B..
2SD1371	Si-NPN	AF, Sw-Pow, 300/300V, 2A, 40W, 5MHz	17j$	Sanyo	TIP75(A..C), BUT93, 2SC2023, 2SC3055..
2SD1372	Si-NPN	AF, Sw-Pow, 300/300V, 4A, 50W, 5MHz	17j$	Sanyo	TIP75(A..C), BUT93, 2SC2907, 2SC2440..
2SD1373	Si-NPN	AF, Sw-Pow, 300/300V, 4A, 50W, 5MHz	18j$	Sanyo	TIP51..54, 2SC2624, 2SC4799
2SD1374	Si-NPN	AF, Sw-Pow, 300/300V, 3A, 50W	23a$	Sanyo	TIP51..54, 2SC4799, 2SD632..
2SD1375	Si-NPN	AF, Sw-Pow, 300/300V, 4A, 90W	23a$	Sanyo	TIP51..54, 2SC4799, 2SD632..
2SD1376(K)	Si-N-Darl+Di	AF, Sw-Pow, 120/120V, 1,5A, 20W, B>2000	14h$	Hit	2SD985..986, 2SD1953, 2SD2019
2SD1377(K)	Si-NPN-Darl	AF, Sw-Pow, 120/120V, 8A, 40W, B>1000	17j$	Hit	BD651, BDT21, BDW73D, BDX53D..
2SD1378	Si-NPN	AF-Pow, 80V, 0,7A, 10W, 120MHz	14h$	Rhm	BD139, BD230, 2SD1382, 2SD1563..
2SD1379	Si-NPN-Darl	AF, Sw-Pow, 40V, 2A, 10W, 150MHz, B>4000	14h$	Rhm	BD775, 2SC4341, 2SD1438, 2SD1953..
2SD138	Si-NPN	AF/Vid-Pow, 200/200V, 1A, 30W	22a$	Fui	BUW40(A,B), TIP47, 2SC783, 2SD1138..
2SD1380	Si-NPN	AF, Sw-Pow, 40V, 2A, 10W, 100MHz	14h$	Rhm	BD375, 2SD1177..78, 2SD1506, 2SD1818,..
2SD1381	Si-NPN	AF, Sw-Pow, 120V, 1A, 5W, 100MHz	14b	Rhm	2SC3421, 2SD1684
2SD1382	Si-NPN	=2SD1381: 10W	14h$	Rhm	2SC2690(A), 2SC2803, 2SD781
2SD1383	Si-NPN-Darl	GenP, 40V, 0,3A, 250MHz, B>1000	?35d	Rhm	-
2SD1383K	Si-NPN-Darl	=2SD1383:	35a	-	BCV27, BCV47, 2SD1478A
2SD1383K-A	Si-NPN-Darl	-	35	Rhm	→2SD1383K
2SD1383K-B	Si-NPN-Darl	-	35	Rhm	→2SD1383K
2SD1383-WA	Si-NPN-Darl	-	?35	Rhm	→2SD1383
2SD1383-WB	Si-NPN-Darl	-	?35	Rhm	→2SD1383
2SD1384	Si-NPN	AF-Dr/Out, 40V, 2A, 0,75W, 100MHz	7c(9mm)	Rhm	2SC3328, 2SC4145, 2SD1146, 2SD1207..
2SD1385	Si-NPN	AF, Vid, 400/400V, 0,1A, 1W, 40MHz	9c	Mat	MPSA45, 2SC2267, 2SC3118, 2SC3469
2SD1386	Si-N-Darl+Di	AF, Sw-Pow, 140V, 8A, 50W, B=4000	17j$	Hit	BDX33E, BDX53E,F, 2SD1500, 2SD1756
2SD1387	Si-NPN	AF-Dr/Out, 20V, 2A, 0,7W, B=250	7c	Sanyo	2SC3225, 2SC3673, 2SD1207, 2SD1835..
2SD1388	Si-NPN	AF-Dr/Out, 60V, 1A, 0,7W, B=250	7c	Sanyo	BC337A, BC637, 2SC3939, 2SD1616(A)..
2SD1389	Si-NPN	Sw, Pow, 1200/650V, 6A, 50W	23a$	Sak	BU546, BU903, 2SC3343..44, 2SD1104..

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2SD139	Si-NPN	=2SD138:300/300V	22a$	Fui	BUW40(A,B),TIP47..50,2SC2022..
2SD1390	Si-NPN	TV-HD,1500/700V,1A,40W	17j$	Mat	BU505
2SD1391	Si-NPN	TV-HD,1500/700V,5A,100W	18j$	Mat	BU706,BU4508AX,2SC3485,2SD954,2SD1496..
2SD1392	Si-N-Darl+Di	60±10V,5A,30W,B>2000	15j$	Nec	(BD645,BD897,BDW23A,BDW63A,..)
2SD1393	Si-N-Darl+Di	60±10V,2A,30W,B>1000	17j$	Sanyo	BD715,BDT61,BDW53A,2SD837..
2SD1394	Si-N-Darl+Di	60±10V,3A,30W,B>1000	17j$	Sanyo	BD715,BDT61,BDW53A,2SD837..
2SD1395	Si-N-Darl+Di	60±10V,5A,40W,B>1000	17j$	Sanyo	BD645,BD897,BDW23A,BDW63A..
2SD1396	Si-NPN+Diode	TV-HD,1500/800V,2,5A,80W	18j$	Sanyo	BU705D,2SC3479,2SD1290..91,2SD1728
2SD1397	Si-NPN+Diode	TV-HD,1500/800V,3,5A,80W	18j$	Sanyo	BU706D,BU4505DX,2SC3480,2SD1729
2SD1398	Si-NPN+Diode	TV-HD,1500/800V,5A,80W	18j$	Sanyo	BU706D,BU4507DX,2SC3481,2SC3681,2SD1730
2SD1399	Si-NPN+Diode	TV-HD,1500/800V,6A,80W	18j$	Sanyo	BU508D,2SC3482,2SC3681,2SD1732
2SD14	Si-NPN	AF,Sw-Pow,75V,10A,100W	38a$	Mat	(BD245B,BDV93,2SC2681)
2SD1400	Si-NPN	TV-HD,1500/800,2,5A,80W	18j$	Sanyo	BU505,BU705,2SC3483,2SD1493..94
2SD1401	Si-NPN	TV-HD,1500/800V,3,5A,80W	18j$	Sanyo	BU706,BU4505AX,2SC3484,2SD1495
2SD1402	Si-NPN	TV-HD,1500/800V,5A,120W	18j$	Sanyo	BU706,BU4507AX,2SC3485,2SC3685,2SD1496
2SD1403	Si-NPN	TV-HD,1500/800V,6A,120W	18j$	Sanyo	BU508A,BU908,BU4508AX,2SC3486,2SD1497
2SD1404	Si-NPN+Diode	TV-HD,300/150V,7/15A,25W,18MHz	17c	Tos	(BU406D..408D,2SC3174,2SC3176)
2SD1405	Si-NPN	=2SD1353:Iso,25W	17c	Tos	2SC3677,2SC3852,2SD1948,2SD1972
2SD1406	Si-NPN	=2SD1354:Iso,25W	17c	Tos	2SC3299,2SC3746,2SD1913,2SD2012..
2SD1407(A)	Si-NPN	=2SD1355:Iso,30W	17c	Tos	2SC3691,2SD1411,2SD1488,2SD1940
2SD1408	Si-NPN	=2SD1356:Iso,25W	17c	Tos	2SC3691,2SC3746,2SC3851,2SD2000
2SD1409(A)	Si-N-Darl+Di	=2SD1360:Iso,25W	17c	Tos	(2SC3579,2SD798..799)
2SD141	SI-NPN	AF,Sw-Pow,20V,2A,15W	22a$	Nec	BD239,BD533,BD933,2N4231..
2SD1410(A)	Si-NPN-Darl	=2SD1361:Iso,25W	17c	Tos	2SD2017,(2SD1088,2SD1113,2SD1976)
2SD1411	Si-NPN	AF,Sw-Pow,Lo-sat,100V,7A,30W.10MHz	17c	Tos	2SC3692,2SC4550
2SD1412(A)	Si-NPN	=2SD1411:70V	17c	Tos	2SC3747
2SD1413	Si-N-Darl+Di	AF,Sw-Pow,60V,3A,20W,B>2000	17c	Tos	BDT61F,2SD1796,2SD1825,2SD1987..
2SD1414	Si-N-Darl+Di	AF,Sw-Pow,100V,4A,20W,B>2000	17c	Tos	2SD1589,2SD1788,2SD1928,2SD2014
2SD1415(A)	Si-N-Darl+Di	=2SD1357:Iso,30W	17c	Tos	2SD1791,2SD1830,2SD2025
2SD1416	Si-N-Darl+Di	=2SD1358:Iso,30W	17c	Tos	2SD1791,2SD1830,2SD2025
2SD1417	Si-N-Darl+Di	=2SD1359:Iso,30W	17c	Tos	2SD1791,2SD1826,2SD2025
2SD1418	Si-NPN	GenP,120/80V,1A,140MHz	39b	Hit	2SC3646,2SD1420..1421
2SD1418-DA	Si-NPN	-	39	Hit	→2SD1418
2SD1418-DB	Si-NPN	-	39	Rhm	→2SD1418
2SD1418-DC	Si-NPN	-	39	Rhm	→2SD1418
2SD1419	Si-NPN	=2SD1418:120/100V	39b	Hit	2SC3646,2SD1420..1421
2SD1419-DD	Si-NPN	-	39	Hit	→2SD1419
2SD1419-DE	Si-NPN	-	39	Hit	→2SD1419
2SD142	Si-NPN	=2SD141:40V	22a$	Nec	BD239,BD533,BD933,2N4231..
2SD1420	SI-NPN	AF-Dr/Out,180/120V,1,5A	39b	Hit	2SC3649
2SD1420-EA	Si-NPN	-	39	Hit	→2SD1420
2SD1420-EB	Si-NPN	-	39	Hit	→2SD1420
2SD1420-EC	Si-NPN	-	39	Hit	→2SD1420
2SD1421	Si-NPN	=2SD1420:180/160V	39b	Hit	2SC3649
2SD1421-ED	Si-NPN	-	39	Hit	→2SD1421
2SD1421-EE	Si-NPN	-	39	Hit	→2SD1421
2SD1422	Si-NPN	AF-Dr/Out,100V,2A	39b	Hit	2SC3647,2SC4132,2SD1420..1421
2SD1423	Si-NPN	=2SD638:0,3W	40c	Mat	→2SD638
2SD1423A	Si-NPN	=2SD639:0,3W	40c	-	→2SD639
2SD1424	Si-NPN	=2SD1010:	40c	Mat	→2SD1010
2SD1425	Si-NPN+Diode	TV-HD,1500/600V,2,5A,80W	77j$	Tos	BU705D,2SC3479,2SD1290..91,2SD1728
2SD1425..1432FI	Si-NPN	=2SD1425..1432:Iso	18c	STE	-
2SD1426	Si-NPN+Diode	TV-HD,1500/600V,3,5A,80W	77j$	Tos	BU706D,BU4506DX,2SC3480,2SD1729
2SD1427	Si-NPN+Diode	TV-HD,1500/600V,5A,80W	77j$	Tos	BU508D,BU2508D,BU4507DX,2SC3481,2SD1730
2SD1428	Si-NPN+Diode	TV-HD,1500/600V,6A,80W	77j$	Tos	BU508D,BU2508D,2SC3482,2SD1731
2SD1429	Si-NPN	TV-HD,1500/600V,2,5A,80W	77j$	Tos	BU505,BU705,2SC3483,2SD1493..94
2SD143	Si-NPN	AF,Sw-Pow,80V,1A,15W	22a$	Nec	BD239B,BD537,BD937,2N4912..
2SD1430	Si-NPN	TV-HD,1500/600V,3,5A,80W	77j$	Tos	BU706,BU4506AX,2SC3484,2SD1495
2SD1431	Si-NPN	TV-HD,1500/600V,5A,80W	77j$	Tos	BU508A,BU908,BU4507AX,2SC3485,2SC3685
2SD1432	Si-NPN	TV-HD,1500/600V,6A,80W	77j$	Tos	BU508A,BU908,BU4508AX,2SC3686,2SD1497
2SD1433	Si-NPN	TV-HD,1500/600V,7A,80W	77j$	Tos	BU508A,BU908,BU2508A,2SC3686..87
2SD1434	Si-NPN	TV-HD,1700/800V,5A,80W	77j$	Tos	-
2SD1435(K)	Si-N-Darl+Di	AF,Sw-Pow,100V,15A,100W,B>1000	18j$	Hit	BDV67A,BDW83C,2SD1026
2SD1436(K)	Si-N-Darl+Di	AF,Sw-Pow,120V,10A,80W,B>1000	18j$	Hit	BDV65C,BDV67B,BDW83D,2SD1210

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2SD1437	Si-NPN	AF,Sw-Pow,80V,3A,40W,8MHz	17j$	Rhm	BD241B,BD537,BD937,2SC3179..
2SD1438	Si-N-Darl+Di	AF,Sw-Pow,80V,2A,15W,B=5000	14h$	Tos	BD679,BD779,2N6039,2SD1376
2SD1439	Si-NPN+Diode	TV-HD,1500V,3A,50W	18j$	Mat	BU706D,BU4506DX,2SC3480,2SD1290..91,2SD1729
2SD144	Si-NPN	=2SD143:100V	22a$	Nec	BD239C,BD937,2SD712,2SD1516..
2SD1440	Si-NPN+Diode	TV-HD,1500V,3A,50W	18j$	Mat	BU706D,BU4505DX,2SC3480,2SD1290..91,2SD1729
2SD1441	Si-NPN+Diode	TV-HD,1500V,4A,70W	18j$	Mat,Tho	BU706D,BU4507DX,2SC3481,2SC3681,2SD1730
2SD1442	Si-NPN	AF,Sw-Pow,Lo-sat,40V,7A,30W,150MHz	17j$	Mat	2SC3254,2SD1235
2SD1442A	Si-NPN	=2SD1442:50V	17j$	-	2SC3254,2SD1235
2SD1443	Si-NPN	AF,Sw-Pow,Lo-sat,40V,10A,40W,120MHz	17j$	Mat	2SC3255,2SC3345,2SD1212
2SD1443A	Si-NPN	=2SD1443:50V	17j$	-	2SC3255,2SC3345,2SD1212
2SD1444(A)	Si-NPN	=2SD1442:Iso	17c	Mat	2SC3747,2SC4327
2SD1445(A)	Si-NPN	=2SD1443(A):Iso	17c	Mat	2SC3709,2SC4064..65
2SD1446	Si-N-Darl+Di	TV-HD,500/400V,6A,40W,B>500	17c	Mat	-
2SD1447	Si-NPN	AF-Dr/Out,30V,1A,0,9W,100MHz	7c(9mm)	Mit	2SC2236,2SD863,2SD1146,2SD1207..
2SD1448(Z)	Si-NPN	AF,Sw-Pow,70V,3A,10W,60MHz	30j$	Nec	2SC3303,2SC3386,2SD1815..16
2SD1449	Si-NPN	=2SD958:0,3W	40c	Mat	→2SD958
2SD1450	Si-NPN	=2SD1302:0,3W	40c	Mat	→2SD1302
2SD1451	Si-NPN	TV-HD,1500/600V,1,5A,50W	18j$	Hit	BU705,2SC3483,2SD1492..94
2SD1452	Si-NPN	TV-HD,1500/600V,2,5A,50W	18j$	Hit	BU705,2SC3483,2SD1493..94
2SD1453	Si-NPN	TV-HD,1500/600V,3A,50W	18j$	Hit	BU706,2SC3484,2SD1495
2SD1454	Si-NPN	TV-HD,1500/600V,4A,50W	18j$	Hit	BU706,2SC3484,2SC3685,2SD1495
2SD1455	Si-NPN	TV-HD,1500/600V,5A,50W	18j$	Hit,Tho	BU706,2SC3485,2SC3685,2SD1496
2SD1456	Si-NPN	TV-HD,1500/600V,6A,50W	18j$	Hit	BU508A,2SC3486,2SC3685,2SD1497
2SD1457(A)	Si-N-Darl+Di	AF,Sw-Pow,200V,6A,60W,15MHz,B>700	16c	Mat	(2SD921,2SD1090,2SD1122..23)
2SD1458	Si-NPN	Hi-beta,Hi-Ueb,20V,0,7A,1W,55MHz	9c	Mat	2SC3070,2SC3616,2SC4204,2SD1582
2SD1459	Si-NPN	CTV-VD,AF-Pow,150V,1,5A,30W,8MHz	17j$	Sanyo	BD239D,2SC2073,2SD608(A),2SD1138..
2SD146(F)	Si-NPN	AF,Sw-Pow,40V,1A,20W	22a$	Fui	BD239,BD533,BD933,2N4910..11..
2SD1460	Si-N-Darl+Di	Sw,Pow,100V,30A,200W,B=4000	23a$	Toshiba	MJ11016,2SD730
2SD1461	Si-N-Darl+Di	Sw,Pow,400V,5A,80W,B>400	18j$	Mat	BU826,2SC3261,2SD663
2SD1462	Si-NPN	AF,Sw-Pow,20V,2A,B=400	30j$	Nec	2SD1583..84
2SD1463	Si-NPN	GenP,120/100V,0,05A,140MHz	39b	Hit	2SC2780,2SC2880,2SC4372,2SD1464
2SD1463-GA	Si-NPN	-	39	Hit	→2SD1463
2SD1463-GB	Si-NPN	-	39	Hit	→2SD1463
2SD1464	Si-NPN	GenP,180/160V,0,05A,140MHz	39b	Hit	2SC2880,2SC4372
2SD1464-HA	Si-NPN	-	39	Hit	→2SD1464
2SD1464-HB	Si-NPN	-	39	Hit	→2SD1464
2SD1465L,S	Si-NPN-Darl	AF,Sw-Pow,120V,1,5A,20W,B>2000	30j$	Hit	2SD1164,(2SD985..986,2SD1376)
2SD1466	Si-N-Darl+Di	Sw,Pow,500/450V,15A,100W,B>200	18j$	Hit	BUT51P
2SD1467	Si-NPN	-		Hit	-
2SD1468(S)	Si-NPN	AF-Dr/Out,30V,1A,0,3..0,4W,150MHz	7c,41c	Rhm	BC337..338,BC635,BC637,2SD1225..
2SD1469(M)	Si-NPN	=2SD1468:0,6W	9c	Rhm	BC337..338,BC635,BC637,2SD1225..
2SD147(F)	Si-NPN	=2SD146:60V	22a$	Fui	BD239A,BD535,BD935,2N4911..12..
2SD1470	Si-NPN-Darl	GenP,60V,1A,B=2k..100k	39b	Hit	BST50..52,2SD1511
2SD1471	Si-NPN-Darl	GenP,40V,0,3A,B=2k..100k	39b	Hit	BCV29,BCV49
2SD1471-DT	Si-N-Darl+Di	-	39	Hit	→2SD1471
2SD1471-ET	Si-N-Darl+Di	-	39	Hit	→2SD1471
2SD1472	Si-N-Darl+Di	GenP,120V,1,5A,B=2k..30k	39b	Hit	-
2SD1473	Si-NPN	AF,Sw,500/400V,0,5A	39b	Hit	2SC4929
2SD1474	Si-NPN	Hi-Ueb,Lo-sat,Hi-beta,100V,6A,40W	17c	Mat	(2SC4553,2SD1947)
2SD1475	Si-NPN	=2SD1476:Iso	17c	Mat	2SC3691,2SC3746,2SC4549,2SC4596..
2SD1476	Si-NPN	AF,Sw-Pow,80V,4A,35W,50MHz	17j$	Mat	BD243B,BD537,BD951,2SC3179..
2SD1477	Si-NPN	GenP,30V,0,1A,0,4W,B=300	9c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SD1478	Si-N-Darl+Di	-	35	Mat	→2SD1478
2SD1478A	Si-N-Darl+Di	-	35	Mat	→2SD1478A
2SD1478A-P	Si-N-Darl+Di	-	35	Mat	→2SD1478A
2SD1478A-Q	Si-N-Darl+Di	-	35	Mat	→2SD1478A
2SD1478A-R	Si-N-Darl+Di	-	35	Mat	→2SD1478A
2SD1478-P	Si-N-Darl+Di	-	35	Mat	→2SD1478
2SD1478-Q	Si-N-Darl+Di	-	35	Mat	→2SD1478
2SD1478-R	Si-N-Darl+Di	-	35	Mat	→2SD1478
2SD1479	Si-NPN	TV-HD,1500/700V,2,5A,80W	18j$	Mat	BU505,BU705,2SC3483,2SD1493..94
2SD148	Si-NPN	AF,Sw-Pow,70V,2A,20W,1,2MHz,-/5,8μS	22a$	Fui	BD239A,BD537,BD937,2N4912..
2SD1480	Si-NPN	AF,Sw-Pow,60V,2A,25W,20MHz	17c	Mat	BD936F,2SD1585,2SD1985,2SD2012..
2SD1481	Si-N-Darl+Di	60±10V,2A,15W,B>2000	17j$	Nec	(BD715,BDW23A,BDWS3B,2SD837,..)

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2SD1482	Si-NPN	GenP,40V,0,1A	35a	Mat	BC846..847,BCW71..72,BCW81..
2SD1483	Si-NPN	-	39	Mat	→2SD1483
2SD1484	Si-NPN	AF,50V,0,5A,250MHz	?35d	Rhm	-
2SD1484K	Si-NPN	=2SD1484:	35a	-	BC817,BCW65..66,2SC3325,2SC3441..
2SD1484K-P	Si-NPN	-	35	Rhm	→2SD1484K
2SD1484K-Q	Si-NPN	-	35	Rhm	→2SD1484K
2SD1484K-R	Si-NPN	-	35	Rhm	→2SD1484K
2SD1485	Si-NPN	=2SD1332:	16c	Mat	2SC4385,2SD2064,(BD245C,2SC2837,..)
2SD1486	Si-NPN	=2SD1333:	16c	Mat	2SC4385,2SD2064,(BD245D,2SC3181,..)
2SD1487	Si-NPN	=2SD1334:	16c	Mat	2SC4386,2SD2052,(BD245D,2SD1046,..)
2SD1488	Si-NPN	=2SD1335:	16c	Mat	2SC4386,2SD2052,(BD245D,2SC2837,..)
2SD1489	Si-NPN	AF-Dr/Out,20V,2A,0,75W,80MHz	7c	Hit	2SC3226,2SD1100,2SD1146,2SD1207..
2SD149	Si-NPN	AF,Sw,70V,1A,0,8W,1,2MHz	2a$	Fui	BC441,BCX40,2N1990,2N2102,2N3109..
2SD1490	Si-NPN	AF-Dr/Out,70V,1A,0,75W,80MHz	7c	Hit	BC639,2SD667,2SD1616(A),2SD1768..
2SD1491	Si-N-Darl+Di	60±10V,±2A,10W,B>2000	14h$	Nec	-
2SD1492	Si-NPN	TV-HD,1500/600V,1,5A,50W	18j$	Hit	BU705,2SC3483
2SD1493	Si-NPN	TV-HD,1500/800V,2,5A,50W	18j$	Hit	BU705,2SC3483
2SD1494	Si-NPN	TV-HD,1500/800V,3A,50W	18j$	Hit	BU706,2SC3484
2SD1495	Si-NPN	TV-HD,1500/600V,4A,50W	18j$	Hit	BU508A,BU2508A,BU706,2SC3484
2SD1496	Si-NPN	TV-HD,1500/600V,5A,50W	18j$	Hit	BU508A,BU908,2SC3485,2SC3685
2SD1497	Si-NPN	TV-HD,1500/650A,6A,50W	18j$	Hit	BU508A,BU908,2SC3486,2SC3685
2SD1498	Si-NPN	TV-HD,1400/650V,8A,50W	18j$	Hit	BU508A,BU908,BU2508A,2SC3687
2SD1499	Si-NPN	=2SD1485: 40W	17c	Mat	BD953F,BDT41AF,2SD1407,2SD1940..
2SD15	Si-NPN	AF,Sw-Pow,60V,6A,80W,<1460/5100nS	23a$	Sak	BD245A,BDV91,2N4914..4915..
2SD150	Si-NPN	AF,Sw-Pow,50V,1A,15W,>10MHz	22a$	Nec	BD239,2SC1398,2SC2591..2592..
2SD1500	Si-N-Darl+Di	AF,Sw-Pow,150V,10A,40W,B=5000	17j$	Tos	2SD1756
2SD1501	Si-NPN	AF-Dr/Out,70V,1A,1W,B=250	9c	Hit	2SD667,2SD774,2SD1616(A),2SD1768..
2SD1502	Si-NPN-Darl	Sw,Pow,300/300V,0,3A,15W,B=7000	17j$	Nec	2SD1798
2SD1503	Si-NPN	TV-HD,900/400V,6A,50W	18j$	Hit	BU508A,BU908,2SC3636,2SC3642
2SD1504	Si-NPN	Muting,30V,0,5A,300MHz,Ron=0,5Ω	41c	Hit	(BC337..338,2SD774,2SC3377,2SD1302+)
2SD1505	Si-NPN	AF,Sw-Pow,60V,3A,30W,90MHz	17j$	Rhm	BD241A,BD535,BD935,2SC3252..
2SD1506	Si-NPN	=2SD1505: 10W	14h$	Rhm	BD177,BD439,BD785,2SD1348..
2SD1507(M)	Si-NPN	=2SD1505: 1W	9c	Rhm	2SC4487,2SD1145,2SD1347,2SD1864
2SD1508	Si-NPN-Darl	AF,Sw-Pow,30V,1,5A,10W,B=7000	14b	Tos	2SD947
2SD1509	Si-N-Darl+Di	AF,Sw-Pow,80V,2A,10W,100MHz,B=5000	14b	Tos	-
2SD151	Si-NPN	AF,Sw-Pow,100V,10A,120W	23a$	Nec	BDY53,2N3055,2N5632..33,2SD426..
2SD1510	Si-N-Darl+Di	AF,Sw-Pow,60V,4A,35W,B>1000	17c	Mat	BDT61F,2SD1796,2SD1825,2SD1987..
2SD1511	Si-NPN-Darl	GenP,100V,1A,150MHz,B>4000	39b	Mat	BST52,2SD1472
2SD1511-Q	Si-N-Darl+Di	-	39	Mat	→2SD1511
2SD1511-R	Si-N-Darl+Di	-	39	Mat	→2SD1511
2SD1511-S	Si-N-Darl+Di	-	39	Mat	→2SD1511
2SD1512	Si-NPN	=2SD1011:	40c	Mat	→2SD1011
2SD1513	Si-NPN	GenP,20V,2A,0,75W,200MHz	7c	Nec	2SC3226,2SD1100,2SD1146,2SD1207..
2SD1514	Si-NPN-Darl	AF,Sw-Pow,100V,15A,100W,B=4000	16j$	Shi	BDV67A,BDW83C,2SD1026
2SD1515	Si-NPN-Darl	=2SD1514: 200V	16j$	Shi	2SD1027
2SD1516	Si-NPN	AF,Sw-Pow,Lo-sat,130V,2A,25W,25MHz	17j$	Mat	2SD1528
2SD1517	Si-NPN	=2SD1516: Iso	17c	Mat	2SD1268
2SD1518	Si-NPN	Sw,Pow,900V,6A,50W,5MHz	18j$	Tos	BU426A,BUW11(A),2SC3153,2SD1503..
2SD1519	Si-NPN	TV-HD,1400/600V,10A,80W	77j$	Tos	BU2520A,2SC3688
2SD152	Si-NPN	AF,Sw-Pow,150V,1A,15W	22a$	Nec	BD239D,2SC2073,2SD608(A),2SD1138..
2SD1520L,S	Si-N-Darl+Di	AF,Sw-Pow,100V,4A,20W,B>1000	30j$	Hit	2SC4345,2SD1223,(BDW23C,BDW53C,..)
2SD1521	Si-N-Darl+Di	50V,1,5A,10W,B>2000	14h$	Hit	(2SC4341,2SD1376,2SD1438)
2SD1522	Si-N-Darl+Di	Sw,Pow,500/450V,10A,100W,B=500	18j$	Hit	BUT51P,2SC3262,2SD979,2SD1298
2SD1523	Si-NPN-Darl	Sw,Pow,450/450V,15A,100W,B=500	18j$	Hit	BUT51P,2SD1466
2SD1524	Si-NPN-Darl	Sw,Pow,450/450V,10A,100W,B=300	18j$	Hit	BUT51P,2SC3262,2SD979,2SD1298
2SD1525	Si-N-Darl+Di	Sw,Pow,100V,30A,150W,B=4000	77j$	Tos	-
2SD1526	Si-NPN	AF-Dr/Out,130V,1A,1W,200MHz	9c	Mat	2N3700..01,2SC2383,2SC3228,2SD1812
2SD1527	Si-NPN	Sw,Pow,1000/1000V,0,5A,25W,5MHz	17j$	Hit	(BUV36A,BUX85,2SC3178,2SC3531,..)
2SD1528	Si-NPN	AF,Sw-Pow,Lo-sat,130V,3A,30W,25MHz	17j$	Mat	2SD959..960
2SD1529	Si-NPN	=2SD1528:	30j$	Mat	2SD1254..55
2SD153	Si-NPN	Sw,Pow,250/200V,10A,120W	49a$	Nec	2N5540
2SD1530	Si-NPN	=2SD1528: Iso	17c	Mat	2SD1268
2SD1531	Si-NPN	AF,Sw-Pow,50V,2A,5W,150MHz	14h$	Mat	BD177,BD235,BD377,2SD1177..78..
2SD1532	Si-NPN-Darl	AF,Sw-Pow,120V,4A,30W,B=3000	17j$	Sak	BDT21,BDW53D,BDW63D,2SD1147..

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2SD1533	Si-NPN-Darl	Sw,Pow,500/400V,7A,50W,20MHz,B>500	17j$	Mat	BU810
2SD1534	Si-NPN-Darl	=2SD1533:	30j$	Mat	2SC4220,2SC4598,(BU810)
2SD1535	Si-NPN-Darl	=2SD1533:Iso	17c	Mat	(BU810)
2SD1536(M)	Si-NPN-Darl	GenP,40V,2A,1W,150MHz,B>1000	9c	Rhm	2SD1786,2SD1861,2SD1931
2SD1537	Si-NPN	AF,Sw-Pow,40V,4A,25W,120MHz	17j$	Mat	2SC2562,2SC3253,2SD1235
2SD1537A	Si-NPN	=2SD1537:50V	17j$	-	2SC2562,2SC3253,2SD1235
2SD1538(A)	Si-NPN	=2SD1537(A):	30j$	Mat	2SD1903,(2SC2562,2SC3253,2SD1235)
2SD1539(A)	Si-NPN	=2SD1537(A):Iso	17c	Mat	2SC3299,2SC4327,2SD1444(A)
2SD154	SI-NPN	AF,Sw-Pow,80V,3A,25W	22a$	Nec	BD241B,BD537,BD937,2SD1505..
2SD1540	Si-NPN-Darl	AF,Sw-Pow,100V,6A,60W,B=800	23a$	Tos	BDV65B,BDX63B,TIP142,2SD1170..
2SD1541	Si-NPN+Diode	TV-HD,1500V,3A,50W	16c	Mat	BU706DF,BU4506DF,2SD1554,2SD1650,2SD1877..
2SD1542	Si-NPN	TV-HD,1500/600V,1,5A,40W	18c	Tos	BU705F,2SD1653,2SD1882
2SD1543	Si-NPN	CTV-HD,1500/600V,2,5A,40W	18c	Tos	BU705F,BU4504AX,2SD1563,2SD1882
2SD1544	Si-NPN	CTV-HD,1500/600V,3,5A,40W	18c	Tos	BU706F,BU4506AX,2SD1654,2SD1883,2SD2381
2SD1545	Si-NPN	CTV-HD,1500/600V,5A,50W	18c	Tos	BU706F,BU4507AX,2SC3894,2SC4142,2SD1655..
2SD1546	Si-NPN	CTV-HD,1500/600V,6A,50W	18c	Tos	BU2508AF,BU4508AX,2SC4143,2SD1556,2SD1885..
2SD1547	Si-NPN	CTV-HD,1500/600V,7A,50W	18c	Tos	BU2508AF,BU4522AX,2SC3895,2SC4757,2SD2252..
2SD1548	Si-NPN	CTV-HD,1400/600V,10A,50W	18c	Tos	BU2520AF,BUH715,2SC3897,2SC4199(A)+
2SD1549	Si-NPN	TV-HD,1000/800V,5A,50W	18c	Tos	BU508AF,BU706F,2SC3884,2SD1885..
2SD155	Si-NPN	AF,Sw-Pow,80V,3A,25W	22a$	Nec	BD241B,BD537,BD937,2SD1505..
2SD1550	Si-NPN	TV-HD,1000/400V,10A,50W	18c	Tos	BU2520AF,2SC3897,2SC4542,2SD1887..
2SD1551	Si-NPN	TV-HD,1500/600V,5A,50W	18c	Tos	BU508AF,2SC3894,2SC4142,2SD1885..
2SD1552	Si-NPN	TV-HD,1500/600V,5A,50W	18c	Tos	BU508AF,2SC3894,2SC4142,2SD1885..
2SD1553	Si-NPN+Diode	TV-HD,1500/600V,2,5A,40W	18c	Tos	BU706DF,BU4504DX,2SD1649,2SD1876,2SD2367
2SD1554	Si-NPN+Diode	TV-HD,1500/600V,3,5A,40W	18c	Tos	BU706DF,BU4506DX,2SD1650,2SD1877,2SD2089
2SD1555	Si-NPN+Diode	TV-HD,1500/600V,5A,50W	18c	Tos	BU508DF,BU4507DX,2SD1651,2SD2095,2SD2125..
2SD1556	Si-NPN+Diode	TV-HD,1500/600V,6A,50W	18c	Tos	BU508DF,BU4508DX,2SC4294,2SD1652,2SD2125..
2SD1557	Si-NPN	AF,Sw-Pow,200V,2A,20W,10MHz	30j$	Nec	2SD1033,2SD1250(A),(2SD1138,..)
2SD1558	Si-NPN-Darl	AF,Sw-Pow,60V,4A,40W,B>1000	17j$	Hit	BD715,BDW23A,BDW53A,2SD837..
2SD1559	Si-N-Darl+Di	AF,Sw-Pow,100V,20A,100W,B>1000	18j$	Hit	2SD1597
2SD156(F)	Si-NPN	Vid-Pow,200V,0,1A,4W(Tc=70°),20MHz	22a$	Fui	2SC1505..1507,2SC1755..1757,2SC1819,..
2SD1562	Si-NPN	AF-Pow,120/120V,1,5A,20W,80MHz	17j$	Rhm	BD239D,BD959,2SC2275,2SD1138..
2SD1562A	Si-NPN	=2SD1562:160/160V	17j$	-	BD239D,2SC2238A,B,2SD608(A),2SD1138..
2SD1563	Si-NPN	=2SD1562:10W	14h$	Rhm	2SC2690(A),2SD781
2SD1563A	Si-NPN	=2SD1563:160/160V	14h$	-	2SC3117,2SD669
2SD1564	Si-N-Darl+Di	50V,5A,30W,B=8000	17j$	Nec	(BDW23A,BDW63A)
2SD1565	Si-N-Darl+Di	Sw,Pow,100/100V,5A,30W,B=8000	17j$	Nec	(BDW23C,BDW63C)
2SD1566	Si-N-Darl+Di	AF,Sw-Pow,150V,±10A,60W,B=9000	15j$	Nec	BDX53F,2SD1500
2SD1567	Si-NPN	AF,Sw-Pow,60V,3A,30W,16MHz	17j$	Nec	BD241A,BD535,BD935,2SC3252..
2SD1568	Si-NPN	AF,Sw-Pow,100V,4A,40W,20MHz	17j$	Nec	BD243C,BD537,BD539C,2SC3253..
2SD1569	Si-NPN	Hi-beta,Lo-sat,60V,3A,30W,B>800	17j$	Nec	-
2SD157(F)	Si-NPN	=2SD156:300/300V	22a$	Fui	2SC1505..1507,2SC1755..1757,2SC1819,..
2SD1571	Si-NPN	Sw,Pow,TV-SMPS,800/400V,3A,30W	17c	Tos	BUT11(A)F,2SC3353,2SC3749,2SC4304,..
2SD1572	Si-NPN-Darl	AF,Sw-Pow,60V,8A,40W,B>1000	17j$	Hit	BD645,BD897,BDW73A,BDX53A..
2SD1573	Si-NPN	AF,Sw,600/600V,0,1A,1W	9c	Hit	-
2SD1574	Si-NPN-Darl	AF,Sw-Pow,100V,1A,10W,B>4000	30j$	Mat	2SD1465,2SD1980
2SD1575	Si-NPN	TV-HD,1500/700V,2A,40W	17c	Mat	BU505F,BU4504AF
2SD1576	Si-NPN	TV-HD,1500/700V,2A,80W	16c	Mat	BU705F,BU4505AF,2SD1543,2SD1653,2SD1882
2SD1577	Si-NPN	TV-HD,1500/700V,5A,100W	16c	Mat	BU2508AF,BU4508AF,2SC3884A,2SC3894,2SC4142
2SD1577FI	Si-NPN	=2SD1577:	18c	STE	→2SD1577
2SD1578	Si-NPN	AF-Dr/Out,30V,0,7A,0,5W,B=550	9c	Hit	2SC3225,2SC4204,2SC4389,2SD1984..
2SD1579	Si-N-Darl+Di	AF,Sw,150V,±1,5A,1W,B>2000	9b	NEC	2SD1659,2SD2213
2SD158(F)	Si-NPN	AF-Pow,Vid-Pow,200/200V,1A,30W,15MHz	22a$	Fui	BUW40,TIP47..50,2SC782,2SC2354..
2SD1580	Si-NPN	AF,Sw-Pow,100V,7A,40W,5MHz	17j$	Rhm	BD243C,BD543C,BD801,2SD550..
2SD1581	Si-NPN	Hi-beta,Hi-Ueb,30V,2A,1W,350MHz	9b	NEC	2SC4389,2SD1779
2SD1582	Si-NPN	Hi-beta,Hi-Ueb,60V,1A,1W,250MHz	9b	NEC	2SD1779
2SD1583(-Z)	Si-NPN	Hi-beta,Lo-sat,30V,2A,B>800,270MHz	30j$	Nec	2SC3474
2SD1584(-Z)	Si-NPN	Hi-beta,Lo-sat,60V,3A,B>800,>50MHz	30j$	Nec	2SD1755
2SD1585	Si-NPN	=2SD1567:Iso,15W	17c	Nec	2SC3690,2SC3851..52,2SD1913
2SD1586	Si-NPN	=2SD1568:Iso,20W	17c	Nec	2SC3691,2SD1407,(BD243C,BD539C,..)
2SD1587	Si-NPN	TV,AF-Pow,200/150V,2A,25W,5MHz	17c	Nec	2SC4382,(BD239F,2SC2660,2SD760,..)
2SD1588	Si-NPN	AF,Sw-Pow,100/60V,7A,30W	17c	Nec	2SC3568,2SC3692,2SC4335,2SD1411
2SD1589	Si-N-Darl+Di	AF,Sw-Pow,100V,±5A,20W,B=8000	17c	Nec	BD647F,2SD1785,2SD1829,2SD1928
2SD159(F)	Si-NPN	=2SD158:300/300V	22a$	Fui	BUW40,TIP47..50,2SC782,2SC2354..

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2SD1590	Si-N-Darl+Di	AF, Sw-Pow, 150V, 8A, 25W, B=6000	17c	Nec	2SD1591, 2SD1792, 2SD1974
2SD1591	Si-N-Darl+Di	AF, Sw-Pow, 150V, 10A, 30W, B=6000	17c	Nec	2SD1794, (2SD1500)
2SD1592	Si-NPN-Darl	R2=500Ω, 500/300V, 5A, 30W, B=1000	17c	Nec	2SD1409
2SD1593	Si-NPN	Hi-beta, Lo-sat, 60V, 3A, 110MHz, B>800	17c	Nec	2SD1972, 2SD2127
2SD1594	Si-NPN	Hi-beta, 100V, 6A, 30W, 110MHz, B>800	17c	Nec	2SC4553, 2SD1947
2SD1595	Si-N-Darl+Di	60V, 5A, 20W, B=6000	17c	Nec	2SD1415..17, 2SD1589, 2SD1826
2SD1597	Si-N-Darl+Di	AF, Sw-Pow, 120V, 30A, 80W, B>1000	18j$	Hit	-
2SD1598	Si-NPN-Darl	AF, Sw-Pow, 60V, 1A, 10W, B=8000	30j$	Nec	2SC2871, 2SD1465, 2SD1164, 2SD1800
2SD1599	Si-NPN-Darl	AF, Sw-Pow, 80V, 4A, 40W, B>1000	17j$	Hit	BDW23B, BDW53B, BDW63B, 2SD837A..
2SD16	Si-NPN	=2SD15: 100V	23a$	Sak	BD245C, BDV95, 2N5758..5759..
2SD160	Si-NPN	AF, Sw-Pow, 100V, 1,5A, 25W, -/3,5µS	2a$	Fui	(BD237, BD239C, BD937, 2SC2275A,..)
2SD1600	Si-NPN-Darl	AF, Sw-Pow, 80V, 8A, 40W, B>1000	17j$	Hit	BD647, BD899, BDW73B, BDX53B..
2SD1601	Si-N-Darl+Di	AF, Sw-Pow, 60V, 4A, 40W, B>1000	17j$	Hit	BD715, BDW23A, BDW53A, 2SD837..
2SD1602	Si-N-Darl+Di	=2SD1601: 80V	17j$	Hit	BD717, BDW23B, BDW53B, 2SD837A..
2SD1603	Si-N-Darl+Di	AF, Sw-Pow, 60V, 8A, 40W, B>1000	17j$	Hit	BD645, BD897, BDW73A, BDX53A..
2SD1604	Si-N-Darl+Di	=2SD1604: 80V	17j$	Hit	BD647, BD899, BDW73B, BDX53B..
2SD1605	Si-N-Darl+Di	AF, Sw-Pow, 120V, 3A, 30W, B>1000	17j$	Hit	BDW53D, BDW63D, 2SD830, 2SD1147..
2SD1606	Si-N-Darl+Di	AF, Sw-Pow, 120V, 6A, 40W, B>1000	17j$	Hit	BDT21, BDW63D, 2SD830, 2SD1147..
2SD1607	Si-N-Darl+Di	AF, Sw-Pow, 120V, 10A, 40W, B=5000	17j$	Hit	BDT63C, BDT65D, BDX33D, 2SD1126
2SD1608	Si-NPN-Darl	AF, Sw-Pow, 120V, 8A, 50W, 20MHz, B>5000	17c	Mat	BD649F, BDT63CF, 2SD1773, 2SD1590..
2SD1609	Si-NPN	AF, Sw-Pow, 160/160V, 0,1A, 140MHz	14h$	Hit	BF415, BF457..459, 2SC3416, 2SC3502,..
2SD161	Si-NPN	AF, Sw-Pow, 120V, 10A, 100W, -/5µS	23a$	Fui	BDX11, 2N3442, 2SD551, 2SD732..733..
2SD1610	Si-NPN	=2SD1609: 200/200V	14h$	Hit	BF415, BF458..459, 2SC3416, 2SC3502,..
2SD1611	Si-N-Darl+Di	Sw, Pow, 500/400V, 6A, 40W, 15MHz, B>500	30j$	Mat	-
2SD1612	Si-N-Darl+Di	AF, Sw-Pow, 120V, 6A, 40W, B=5000	15j$	Hit	BDW63D, BDW73D, BDX53D, 2SD1147..
2SD1613	Si-N-Darl+Di	AF, Sw-Pow, 120V, 8A, 40W, B=5000	15j$	Hit	BDW73D, BDX33D, BDX53D, 2SD651..
2SD1614	Si-NPN	GenP, 40V, 2A, 200MHz	39b	Nec	2SC2873, 2SD1119, 2SD1766
2SD1614-XK	Si-NPN	-	39	Nec	→2SD1614
2SD1614-XL	Si-NPN	-	39	Nec	→2SD1614
2SD1614-XM	Si-NPN	-	39	Nec	→2SD1614
2SD1615	Si-NPN	GenP, Lo-sat, 60V, 1A, >80MHz	39b	Nec	2SC3444, 2SD1622..23, 2SC4409
2SD1615A	Si-NPN	=2SD1615: 120V	39b	-	(2SC3646, 2SD1418..19)
2SD1615A-GP	Si-NPN	-	39	Nec	→2SD1615A
2SD1615A-GQ	Si-NPN	-	39	Nec	→2SD1615A
2SD1615-GK	Si-NPN	-	39	Nec	→2SD1615
2SD1615-GL	Si-NPN	-	39	Nec	→2SD1615
2SD1615-GM	Si-NPN	-	39	Nec	→2SD1615
2SD1616	Si-NPN	Lo-sat, 60V, 1A, 0,75W, 160MHz	7c	Nec	2SC4485..86, 2SD1207, 2SD1835
2SD1616A	Si-NPN	=2SD1616: 120V	7c	-	2SC4488..89, (2SD1812, 2SD1857,..)
2SD1617	Si-NPN	AF-Pow, Lo-sat, 40V, 3A, 1W, 200MHz	9b	NEC	2SC4487, 2SD1347
2SD1618	Si-NPN	AF, Lo-sat, 20V, 0,7A, 250MHz	39b	Sanyo	2SC2982, 2SC3443
2SD1619	Si-NPN	AF, 25V, 1A, 180MHz	39b	Sanyo	BC868, BCX68, BCX54..56, 2SC3444..
2SD162	Ge-NPN	AF, 20V, 0,03A, 0,65W	37a	Fui	-
2SD1620	Si-NPN	AF, Lo-sat, 30V, 3A, 200MHz	39b	Sanyo	2SC4541, 2SD1624
2SD1621	Si-NPN	AF, Lo-sat, 30V, 2A, 150MHz	39b	Sanyo	2SC2982, 2SD1620
2SD1622	Si-NPN	AF, Lo-sat, 60V, 1A, 150MHz	39b	Sanyo	2SC3444, 2SC1615, 2SC5026
2SD1623	Si-NPN	AF, Lo-sat, 60V, 2A, 150MHz	39b	Sanyo	2SC4409
2SD1624	Si-NPN	AF, Lo-sat, 60V, 3A, 150MHz	39b	Sanyo	2SC4541
2SD1625	Si-NPN-Darl	AF, 80V, 0,7A, B>5000, 200MHz	39b	Sanyo	BST51..52, 2SD1511
2SD1626	Si-NPN-Darl	AF, 80V, 1,5A, B>4000, 120MHz	39b	Sanyo	2SD1472
2SD1627	Si-NPN-Darl	AF, 30V, 2A, B>4000, 120MHz	39b	Sanyo	2SD1784
2SD1628	Si-NPN	AF, Lo-sat, 60V, 5A, 30/340nS	39b	Sanyo	-
2SD1629	Si-N-Darl+Di	60V, 1,2A, 10W, B>2000	17j$	Nec	-
2SD163	Si-NPN	AF, Sw-Pow, 60V, 10A, 100W, 1,56/6µS	23a$	Sak	BD311, 2N3055, 2N5632..33, 2SD426..
2SD1630	Si-N-Darl+Di	60V, 1A, 10W, B>2000	14h$	Nec	2SC4340..41
2SD1631	Si-NPN-Darl	=2SD1140: 1W	9c	Tos	2SD1536, 2SD1786, 2SD1861, 2SD2046..
2SD1632	Si-NPN+Diode	Sw, Pow, TV-HD, 1500V, 4A, 70W	16c	Mat	BU508DF, 2SD1554, 2SD1650, 2SD2089..
2SD1633	Si-NPN-Darl	AF, Sw-Pow, 100V, 5A, 30W, 15MHz, B>1500	17c	Mat	2SD1589, 2SD1785, 2SD1829, 2SD1928..
2SD1634	Si-NPN-Darl	AF, Sw-Pow, 100V, 8A, 50W, 15MHz, B>1500	17c	Mat	2SD1415, 2SD1590..91, 2SD1791
2SD1635	Si-N-Darl+Di	Sw, Pow, 1500V, 5A, 100W, B=100	23a$	Matsushita	-
2SD1636	Si-NPN	AF/Vid, 300V, 0,07A, 1W, 80MHz	9c	Mat	BF299, BF487, BF420A, 2SC3468..
2SD1637	Si-N-Darl+Di	60V, 2A, 15W, B>1000	14h$	Rhm	-
2SD1638	Si-N-Darl+Di	AF, Sw-Pow, 100V, 2A, 15W, B=1k..10k	14h$	Rhm	2SD1376, 2SD1953
2SD1639	Si-NPN	AF, Sw-Pow, 100V, 2,2A, 10W(Tc=25°)	2a$	Mit	BUY41, 2N4300, 2SC1680

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2SD164	Si-NPN	=2SD163:100V	23a$	Sak	BD317,2N3055,2N5632..33,2SD426..
2SD1640	Si-N-Darl+Di	AF,Sw-Pow,120V,2A,150MHz,B>4000	14b	Mat	-
2SD1641	Si-NPN	Hi-beta,Z-Di,55V,4A,80W,45MHz,B>500	18j$	Mat	-
2SD1642	Si-NPN	AF,100V,2A,0,7W	7c	Hit	2SC4489,2SD1015,2SD2182
2SD1643	Si-NPN	Hi-beta,80V,3A,50W,50MHz,B>500	16c	Mat	-
2SD1643A	Si-NPN	=2SD1643:100V	16c	-	-
2SD1644	Si-N-Darl+Di	+Z-Di(B→C),95V,1A,B=10000	39b	Mat	2SD1511,BST52
2SD1645	Si-N-Darl+Di	60V,1A,150MHz,B=4k..40k	14h$	Mat	-
2SD1646	Si-N-Darl+Di	=2SD1638:25W	17j$	Rhm	BDT61B,BDW53C,2SD837B
2SD1647	Si-N-Darl+Di	=2SD1637:25W	17J$	Rhm	-
2SD1648	Si-NPN	AF,30V,0,02A	35c	Sanyo	-
2SD1649	Si-NPN+Diode	TV-HD,1500/800V,2,5A,50W	18c	Sanyo	2SD705DF,2SD1553,2SD1876,2SD2367,BU4504DX
2SD165	Si-NPN	=2SD163:150V	23a$	Sak	BDX11,2N3442,2SD551,2SD732..733..
2SD1650	Si-NPN+Diode	TV-HD,1500/800V,3,5A,50W	18c	Sanyo	BU706DF,BU4505DX,2SD1554,2SD1877,2SD2089
2SD1650FI	Si-NPN+Diode	TV-HD,1500/800V,3,5A,50W,B>8	18c	STE	BU706DF,2SD1554,2SD1877,2SD2089
2SD1651	Si-NPN+Diode	TV-HD,1500/800V,5A,60W	18c	Sanyo	BU2508DF,BU4507DX,2SD1555,2SD2095,2SD2125..
2SD1652	Si-NPN+Diode	TV-HD,1500/800V,6A,60W	18c	Sanyo	BU2508DF,BU4508DX,2SC4293,2SD1556,2SD2125..
2SD1653	Si-NPN	TV-HD,1500/800V,2,5A,50W	18c	Sanyo	BU705F,BU4504AX,2SD1543,2SD1882,(2SC3483,..)
2SD1654	Si-NPN	TV-HD,1500/800V,3,5A,50W	18c	Sanyo	BU706F,BU4505AX,2SD1544,2SD1883,(2SC3484,..)
2SD1655	Si-NPN	TV-HD,1500/800V,5A,50W	18c	Sanyo	BU2508AF,BU4507AX,2SC3894,2SC4142,2SD1545..
2SD1656	Si-NPN	TV-HD,1500/800V,6A,50W	18c	Sanyo	BU2508AF,BU4508AX,2SC3894,2SC4294,2SD1546..
2SD1657	Si-NPN	AF,25V,0,7A,0,6W,150MHz	7c	Mat	BC337..338,BC635,BC637,2SD1578..
2SD1658	Si-N-Darl+Di	+Z-Di(B→C),60V,2A,10W,B=5000	14b	Tos	-
2SD1659	Si-N-Darl+Di	AF,Sw,150V,±1,5A,1W,B=10000	9b	NEC	2SD1579,2SC2213
2SD166	Si-NPN	AF,Pow-Sw,200V,10A,100W,B>15	23a$	Sanken	2SC1585..86,2SD665,BDW16,MJ15015..
2SD1660(M)	Si-N-Darl+Di	=2SD1638:1W	9c	Rhm	2SD1978,2SD1981,2SD2067,2SD2206..
2SD1661(M)	Si-N-Darl+Di	=2SD1637:1W	9a	Rhm	-
2SD1662	Si-N-Darl+Di	AF,Sw-Pow,100V,15A,100W,B=5000	18j$	Tos	BDV67A,BDW83C,2SD1026
2SD1663	Si-NPN	TV-HD,1500V,5A,80W	16c	Mat	BU706,BU4508AF,2SC3884A,2SC3894,2SD1655..
2SD1664	Si-NPN	AF,40V,1A,150MHz	39b	Rhm	BCX54..56,2SC3444,2SD874A..
2SD1664-P	Si-NPN	-	39	Rhm	→2SD1664
2SD1664-Q	Si-NPN	-	39	Rhm	→2SD1664
2SD1664-R	Si-NPN	-	39	Rhm	→2SD1664
2SD1665(M)	Si-NPN	GenP,120/120V,1,5A,1W,80MHz	9c	Rhm	2SD1015,2SD1812,2SD1857
2SD1665A(M)	Si-NPN	=2SD1665:160/160V	9c	Sanyo	2SD1812,2SD1857A,2SC4614
2SD1666	Si-NPN	AF,Sw-Pow,60V,3A,25W,8MHz	17c	Sanyo	2SC3299,2SC3852,2SD1585,2SD2012..
2SD1667	Si-NPN	Sw,Pow,Lo-sat,60V,5A,25W,30MHz	17c	Sanyo	2SC3299,2SC3746,2SD1411
2SD1668	Si-NPN	Sw,Pow,Lo-sat,60V,7A,30W,10MHz	17c	Sanyo	2SC3747,2SD1412
2SD1669	Si-NPN	Sw,Pow,Lo-sat,60V,12A,30W,10MHz	17c	Sanyo	2SC3709,2SC4065
2SD167	Ge-NPN	AF-Dr/Out,20V,0,5A,0,2W	2a	Fui	AC127,AC176,AC187,2SD72,2SD352
2SD1670	Si-N-Darl+Di	Sw,Pow,150/100V,±10A,65W,B=9000	18c	Nec	2SD1895
2SD1671	Si-N-Darl+Di	Sw,Pow,150/100V,±15A,70W,B=3500	18c	Nec	-
2SD1672	Si-N-Darl+Di	Sw,Pow,150/100V,25A,70W,B=3500	18c	Nec	-
2SD1673	Si-N-Darl+Di	Sw,Pow,500/400V,10A,70W,B=600	18c	Nec	(BU922,BUW81,MJ10003,2SD685,..)
2SD1676	Si-NPN-Digital	Sw,20V,0,6A,0,3W,R1=R2=6,8ke	41c	Hit	DTC363ES
2SD1677	Si-NPN	TV-HD,1500/800V,5A,100W	18j$	Sanyo	BU508A,BU908,BU4508AX,2SC3485,2SC3685..
2SD1678	Si-N-Darl+Di	AF,Sw-Pow,100V,15A,100W,B=5000	20j$	Tos	2SD1087,2SD1129
2SD1679	Si-NPN+Diode	18V,0,5A,170MHz	3Sa	Mat	-
2SD1679-R	Si-NPN	-	35	Mat	→2SD1679
2SD1679-S	Si-NPN	-	35	Mat	→2SD1679
2SD1679-T	Si-NPN	-	35	Mat	→2SD1679
2SD168	Si-NPN-Darl	AF,Sw-Pow,80V,10A,50W,B=2500	23a$	Fui	BDV65A,BDX83B,BDX85B,MJ3000..01,..
2SD1680	Si-NPN	TV-HD,Sw,Pow,330/200V,7A,70W,30MHz	16c	Mat	(BU124(A),2SC2305,2SC2656,2SD917)
2SD1681	Si-NPN	AF,Sw-Pow,Lo-sat,20V,1,2A,10W,150MHz	14b	Sanyo	2SC3244,(BD135,BD226,..)
2SD1682	Si-NPN	Sw,Pow,Lo-sat,60V,2,5A,10W,140MHz	14b	-	(BD785,2SD1348,..)
2SD1683	Si-NPN	Sw,Pow,Lo-sat,60V,4A,10W,150MHz	14b	Sanyo	(BD785,2SD1348,..)
2SD1684	Si-NPN	AF,Sw-Pow,Lo-sat,120V,1,5A,10W,120MHz	14b	Sanyo	2SC3621,(2SC2481,2SC2690(A))
2SD1685	Si-NPN	AF,Sw-Pow,Lo-sat,60V,5A,10W,120MHz	14b	Sanyo	(BDX35..37,2SD826)
2SD1686	Si-N-Darl+Di	AF,Sw-Pow,120V,3A,20W,B=5000	15c	Hit	2SD1785,2SD2015,(BDW53D,BDW63D,..)
2SD1687	Si-N-Darl+Di	AF,Sw-Pow,60V,3A,20W,B=5000	15c	Hit	BDT61F,2SD1413,2SD1796,2SD1987..
2SD1688	Si-N-Darl+Di	AF,Sw-Pow,120V,8A,25W,B=7000	15c	Hit	BD649F,2SD1590..91,2SD1773
2SD1689	Si-N-Darl+Di	AF,Sw-Pow,120V,6A,25W,B=5000	15c	Hit	BD649F,2SD1336,2SD1773,2SD1785..
2SD1690	Si-N-Darl+Di	AF,Sw-Pow,120V,8A,25W,B=5000	15c	Hit	BD649F,2SD1590..91,2SD1773,2SD1792..
2SD1691	Si-NPN	Lo-sat,60V,5A,20W,<1/3,5μS	14h$	Nec	2SD826

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2SD1692	Si-N-Darl+Di	AF,Sw-Pow,150V,3A,15W,B>2000	14h$	Nec	2SC4342
2SD1693	Si-N-Darl+Di	AF,Sw-Pow,Iint.Z-Di,60V,3A,15W,B>2000	14h$	Nec	-
2SD1694	Si-NPN	Hi-beta,Lo-sat,60V,3A,20W,B>800	14h$	Nec	-
2SD1695	Si-N-Darl+Di	31V,±2A,B>2000	14h$	Nec	-
2SD1696	Si-N-Darl+Di	±4A,B=10000	14h$	Nec	-
2SD1697	Si-N-Darl+Di	AF,Sw,100V,±0,8A,1W,B>4000	9b	NEC	2SC1879,2SD1660,2SD1978,2SD1981..
2SD1698	Si-N-Darl+Di	=2SD1697:0,75W	7c	Nec	→2SD1697
2SD1699	Si-N-Darl+Di	=2SD1697:SMD	39b	Nec	BST52,2SD1511
2SD1699-TQ	Si-N-Darl+Di	-	39	Nec	→2SD1699
2SD1699-TR	Si-N-Darl+Di	-	39	Nec	→2SD1699
2SD17	Si-NPN	=2SD15:150V	23a$	Sak	BD245D,BDX11,2N3442,2SD731..732..
2SD170	Ge-NPN	AF-Dr/Out,25V,0,5A,0,2W	2a	Hit	AC127,AC176,AC187,2SD72,2SD352
2SD1700	Si-N-Darl+Di	=2SD1697:Int.Z-Diode(B>C),60±10V	9b	Nec	-
2SD1701	Si-N-Darl+Di	=2SD1698:Int.Z-Diode(B>C),60±10V	7c	Nec	-
2SD1702	Si-N-Darl+Di	=2SD1699:Int.Z-Diode(B>C),60±10V	39b	Nec	-
2SD1702-TE	Si-N-Darl+Di	-	39	Nec	→2SD1702
2SD1702-TF	Si-N-Darl+Di	-	39	Nec	→2SD1702
2SD1703	Si-NPN	AF,Sw-Pow,160/160V,12A,120W	18j$	Mat	BD745F,2SC3907,2SD1047
2SD1704	Si-NPN	AF,Sw-Pow,170/170V,15A,150W	77J$	Mat	2SC3281,2SD1718,2SD1975,2SD2155
2SD1705	Si-NPN	AF,Sw-Pow,130/80V,10A,70W,20MHz	16c	Mat	2SC4690,(BD245D,2SC2706,2SC2837)
2SD1706	Si-NPN	AF,Sw-Pow,130/80V,15A,80W,20MHz	16c	Mat	2SC3762,2SC4886,(BD745E,2SC2987A,..)
2SD1707	Si-NPN	AF,Sw-Pow,130/80V,20A,100W,20MHz	16c	Mat	(BD745E,BD249D)
2SD1708	Si-N-Darl+Di	AF,Sw-Pow,120V,2A,B=6000	?14b	Tos	(2SD1376,2SD1953)
2SD1709	Si-NPN+Diode	TV-HD,1500/800V,5A,100W	18j$	Sanyo	BU508D,2SC3481,2SC3681,2SC4291..
2SD170A	Ge-NPN	=2SD170:32V	2a	-	AC127,AC176,2SD352
2SD1710	Si-NPN	TV-HD,1500/800V,5A,50W	18c	Sanyo	BU508AF,BU4508AX,2SC3894,2SC4142,2SD1655..
2SD1711	Si-NPN+Diode	TV-HD,1500/800V,5A,100W	18c	Sanyo	BU508DF,BU4508DX,2SC4122,2SC4293,2SD1555..
2SD171-1,-2	Ge-NPN	Sw,Pow,-1=450V,-2=600V,3,5A,125W	23a$	Sony	BU511(A),BUX47(A),2SC3156,2SD640,..
2SD1712	Si-NPN	AF,Sw-Pow,100V,5A,60W,20MHz	16c	Mat	2SC4385,2SC5099,2SD2064..65
2SD1713	Si-NPN	AF,Sw-Pow,120V,6A,70W,20MHz	16c	Mat	2SC4385,2SC5099,2SD2064..65
2SD1714	Si-NPN	AF,Sw-Pow,140V,7A,80W,20MHz	16c	Mat	2SD2065,(BD245D,2SC2837,2SD1046,..)
2SD1715	Si-NPN	AF,Sw-Pow,150V,9A,100W,20MHz	16c	Mat	2SC4386,2SC5100,2SD2052
2SD1716	Si-NPN	AF,Sw-Pow,160V,12A,120W,20MHz	16c	Mat	2SC3762,2SC4886,(BD745F,2SC2987A,..)
2SD1717	Si-NPN	AF,Sw-Pow,160V,12A,120W,20MHz	77j$	Mat	2SC3280..3281,2SD1704,2SD2029
2SD1718	Si-NPN	AF,Sw-Pow,180V,15A,150W,20MHz	77j$	Mat	2SC3281,2SD1975,2SD2155
2SD1719	Si-NPN	Hi-beta,Hi-Ueb,Lo-sat,100V,6A,40W	30j$	Mat	-
2SD172	Si-NPN	AF,Sw-Pow,60V,10A,100W	23a$	Fui	BD245A,BD315,2N3055,2N5877..78..
2SD1720	Si-NPN	AF-Pow,80V,5A,40W,8MHz	17j$	Rhm	BD243B,BD543B,BD951,2SD613..
2SD1721	Si-NPN	AF-Dr/Out,60V,2A,1W	9b	NEC	MPS650..651,2SC3328,2SD1207..
2SD1722	Si-NPN	Sw,Pow,Lo-sat,60V,5A,20W,180MHz	?14h$	Sanyo	2SD826,2SD1685
2SD1723	Si-NPN	Sw,Pow,Lo-sat,60V,8A,20W,180MHz	?14h$	Sanyo	-
2SD1724	Si-NPN	Sw,Pow,Lo-sat,120V,3A,20W,180MHz	?14h$	Sanyo	-
2SD1725	Si-NPN	Sw,Pow,Lo-sat,120V,4A,20W,180MHz	?14h$	Sanyo	-
2SD1726	Si-NPN-Darl	AF,Sw-Pow,150/100V,7A,25W,B>1500	17c	Fjd	2SD1590..91
2SD1727	Si-NPN+Diode	TV-HD,1500/700V,1,5A,60W	18j$	Mat	BU705D,2SC3479,2SD1290..1291
2SD1728	Si-NPN+Diode	TV-HD,1500/700V,2,5A,60W	18j$	Mat	BU705D,BU4505DX,2SC3479,2SD1290..1291
2SD1729	Si-NPN+Diode	TV-HD,1500/700V,3,5A,60W	18j$	Mat	BU706D,BU4507DX,2SC3480
2SD173	Si-NPN	=2SD172:100V	23a$	Fui	BD245C,BD317,2N3055,2N5632..33..
2SD1730	Si-NPN+Diode	TV-HD,1500/700V,5A,100W	18J$	Mat	BU508D,BU4507DX,2SC3481,2SC3681,2SC4291
2SD1731	Si-NPN+Diode	TV-HD,1500/700V,6A,100W	18j$	Mat	BU508D,BU2520DW,2SC3482,2SC3681,2SC4292..
2SD1732	Si-NPN+Diode	TV-HD,1500/700V,7A,120W	18j$	Mat	BU508D,BU2508D,BU4523DW,2SC3682..3683
2SD1733(FS)	Si-NPN	AF-Out/Pow,120V,1A,10W,100MHz	30j$	Rhm	2SC4134,2SD1074..75,2SD1283..1284..
2SD1734	Si-NPN	TV-HD,1500/700V,1,5A,40W	17c	Mat	BU505F,2SD1575,(2SD1390)
2SD1735	Si-NPN	TV-HD,1500/700V,1,5A,60W	16c	Mat	BU705F,2SD1542,2SD1653,2SD1882
2SD1736	Si-NPN	TV-HD,1500/700V,2,5A,60W	16c	Mat	BU705F,BU4505AF,2SD1543,2SD1653,2SD1882
2SD1737	Si-NPN	TV-HD,1500/700V,3,5A,60W	16c	Mat	BU706F,2SD1544,2SD1654,2SD1883
2SD1738	Si-NPN	TV-HD,1500/700V,5A,100W	16c	Mat	BU706F,BU4508AF,2SD1545,2SD1655,2SD1884
2SD1739	Si-NPN	TV-HD,1500/700V,6A,100W	16c	Mat	BU508AF,BU4522AF,2SD1546,2SD1656,2SD1885
2SD174(F)	Si-NPN	AF,Sw-Pow,60V,5A,50W	23a$	Fui	BD245A,BDV91,BDX91,2N5873..74..
2SD1740	Si-NPN-Darl	AF,Sw-Pow,150/100V,5A,30W,B>700	17c	Fjd	2SD1590,2SD1315,2SD1336
2SD1741(A)	Si-NPN	=2SD1250(A):15W	?30j$	Mat	2SD1033,2SD1557
2SD1742	Si-NPN	=2SD1252(A):15W	?30j$	Mat	2SC3386,2SD1221,2SD1802
2SD1743	Si-NPN	=2SD1253(A):15W	?30j$	Mat	2SC3074,2SC3518,2SC3592,2SD1803
2SD1744	Si-NPN	=2SD1254:15W	?30j$	Mat	-

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2SD1745	Si-NPN	=2SD1255: 15W	?30j$	Mat	-
2SD1746	Si-NPN	=2SD1256: 15W	?30j$	Mat	-
2SD1747(A)	Si-NPN	=2SD1257(A): 15W	?30j$	Mat	-
2SD1748(A)	Si-N-Darl+Di	=2SD1260(A): 15W	?30j$	Mat	2SD1222,2SD1817
2SD1749(A)	Si-N-Darl+Di	=2SD1261(A): 15W	?30j$	Mat	2SD1223,2SD1520
2SD175(F)	Si-NPN	=2SD174: 100V	23a$	Fui	BD245C,BDV95,BDX95,2N5758..59..
2SD1750(A)	Si-N-Darl+Di	=2SD1262(A): 15W	?30j$	Mat	-
2SD1751	Si-NPN	=2SD1480: 15W	?30j$	Mat	2SD1079,2SD1281..1282
2SD1752(A)	Si-NPN	=2SD1445(A): 15W	?30j$	Mat	-
2SD1753	Si-NPN	=2SD1258: 15W	?30j$	Mat	-
2SD1754(A)	Si-NPN	=2SD1259(A): 15W	?30j$	Mat	-
2SD1755	Si-NPN	=2SD1719: 15W	?30j$	Mat	-
2SD1756	Si-NPN-Darl	AF,Sw-Pow,200/200V,10A,40W,B>1500	17j$	Hit	-
2SD1757K	Si-NPN	Lo-sat,30V,0,5A,150MHz	35a	Rhm	2SC3265,2SC4519
2SD1757K-Q	Si-NPN	-	35	Rhm	→2SD1757K
2SD1757K-R	Si-NPN	-	35	Rhm	→2SD1757K
2SD1757K-S	Si-NPN	-	35	Rhm	→2SD1757K
2SD1758(F5)	Si-NPN	AF-Out/Pow,40V,2A,10W,100MHz	30j$	Rhm	2SC3076,2SD1078..79,2SD1801..
2SD1759(F5)	Si-NPN-Darl	AF-Out/Pow,40V,2A,10W,B>1000	30j$	Rhm	2SD1222,2SD1817,(BD411..412,MPSU45)
2SD176	Si-NPN	AF,Sw-Pow,90V,10A,100W	23a$	Fui	BD245C,BD317,2N3055,2N5632..33..
2SD1760(F5)	Si-NPN	AF-Out/Pow,60V,3A,15W,90MHz	30j$	Rhm	2SC3592,2SC3386,2SD1221,2SD1802..
2SD1761	Si-NPN	AF-Out/Pow,80V,3A,30W,8MHz	17c	Rhm	2SC3690,2SC3746,2SC3851,2SD1586..
2SD1762	Si-NPN	AF-Pow,60V,3A,25W,70MHz	17c	Rhm	2SC3299,2SC3690..91,2SC3746,2SD1913
2SD1763	Si-NPN	AF-Out,120/120V,1,5A,20W,80MHz	17c	Rhm	2SC3298(A,B),2SC3364,2SC3564,2SC4370
2SD1763A	Si-NPN	=2SD1763: 160/160V	17c	-	2SC3298(A,B),2SC4159,2SC4370,2SC4883A
2SD1764	Si-N-Darl+Di	60V,2A,20W,B>1000	17c	Rhm	(BDT61F,2SD1413,2SD1796,2SD1825..)
2SD1765	Si-N-Darl+Di	AF,Sw-Pow,100V,2A,20W,B>1000	17c	Rhm	2SD1414,2SD1788,2SD1828,2SD2015..
2SD1766	Si-NPN	AF,40V,2A,100MHz	39b	Rhm	2SC2873,2SD1623,2SD1766
2SD1766-P	Si-NPN	-	39	Rhm	→2SD1766
2SD1766-Q	Si-NPN	-	39	Rhm	→2SD1766
2SD1766-R	Si-NPN	-	39	Rhm	→2SD1766
2SD1767	Si-NPN	AF,80V,0,7A,120MHz	39b	Rhm	BCX56,2SD1005,2SD1368,2SD1418..19
2SD1767-P	Si-NPN	-	39	Rhm	→2SD1767
2SD1767-Q	Si-NPN	-	39	Rhm	→2SD1767
2SD1767-R	Si-NPN	-	39	Rhm	→2SD1767
2SD1768(S)	Si-NPN	AF-Dr/Out,100V,1A,0,3W,100MHz	41c	Rhm	BC639,2SD667,2SD774,2SD1616A..
2SD1769	Si-N-Darl+Di	Sw,Pow,120/120V,6A,50W,100MHz,B>2000	17j$	Sak	(BD651,BDT21,BDW73D,BDX53D,..)
2SD177(M)	Si-NPN	=2SD176: 120V	23a$	Fui	BDX11,2N3442,2SD551,2SD732..733..
2SD1770	Si-NPN	AF-Pow,200/150V,1A,25W,20MHz	17j$	Mat	BD239F,2SC2238B,2SD387(A),2SD1138
2SD1770A	Si-NPN	=2SD1770: 200/180V	17j$	-	BD239F,2SC2238B,2SD387(A),2SD1138
2SD1771(A)	Si-NPN	=2SD1770(A):	30j$	Mat	2SD1250,(BD239F,2SC2238B),2SD1138)
2SD1772(A)	Si-NPN	=2SD1770(A): Iso	17c	Mat	2SC3298B,2SC4382,2SD1587,2SD2337
2SD1773	Si-NPN-Darl	AF,Sw-Pow,120/120V,8A,50W,20MHz,B>1000	17c	Mat	BD649F,BDT63CF,2SD1590..91
2SD1774	Si-NPN	Hi-beta,80V,2A,25W,40MHz,B>500	17j$	Mat	2SC3852,2SD1157,2SD1943,2SC1983
2SD1774A	Si-NPN	=2SD1774: 100V	17j$	-	-
2SD1775(A)	Si-NPN	=2SD1774(A):	30j$	Mat	2SD1259(A)
2SD1776(A)	Si-NPN	=2SD1774(A): Iso	17c	Mat	2SD1273(A),2SD1944,2SD2092
2SD1777	Si-NPN	-	44	Hit	→2SD1777
2SD1778(A)	Si-NPN	AF,Sw-Pow,80V,4A,40W,8MHz	17j$	Rhm	BD243B,BD537,BD951,2SC3179..
2SD1779	Si-NPN	Hi-beta,Hi-Ueb,60V,2A,1W,B>800	9b	NEC	-
2SD178	Ge-NPN	AF,20V,0,3A,0,225W	2a	Mat	AC127,AC176,AC187,2SD72,2SD352
2SD1780	Si-NPN	=2SD1779: integr. Z-Diode(C>B)	9b	Nec	-
2SD1781K	Si-NPN	Lo-sat,40V,0,8A,150MHz	35a	Rhm	(BCW65..66,BCX41)
2SD1781K-P	Si-NPN	-	35	Rhm	→2SD1781K
2SD1781K-Q	Si-NPN	-	35	Rhm	→2SD1781K
2SD1781K-R	Si-NPN	-	35	Rhm	→2SD1781K
2SD1782K	Si-NPN	AF-Dr/Out,80V,0,5A,180MHz	35a	Rhm	BCW66,BCX41
2SD1782K-P	Si-NPN	-	35	Rhm	→2SD1782K
2SD1782K-Q	Si-NPN	-	35	Rhm	→2SD1782K
2SD1782K-R	Si-NPN	-	35	Rhm	→2SD1782K
2SD1783	Si-N-Darl+Di	60V,5A,30W,B>2000	17j$	Rhm	BD645,BD897,BDW23A,BDW63A..
2SD1784	Si-NPN	-	39	Tos	→2SD1784
2SD1785	Si-N-Darl+Di	AF,Sw-Pow,120V,6A,30W,100MHz,B>2000	17c	Sak	(2SD1336,2SD1590)
2SD1786	Si-NPN-Darl	AF-Dr/Out,40V,2A,0,9W,B=20000	7c(9mm)	Rhm	2SD1153,2SD1536,2SD1861,2SD1929..

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2SD1787	Si-NPN	AF,50V,0,5A,0,4W,250MHz	9c	Rhm	BC337,BC635,BC637,2SD1226..
2SD1788	Si-N-Darl+Di	Sw,Pow,100/100V,±4A,25W,50MHz,B>1,5k	15c	Shi	2SD1891..92,2SD2014
2SD1789	Si-N-Darl+Di	Sw,Pow,200/200V,±4A,25W,20MHz,B>1,5k	15c	Shi	-
2SD178A	Ge-NPN	=2SD178:40V	2a	-	(AC127,AC176,2SD352)
2SD178B	Ge-NPN	=2SD178:60V	2a	-	-
2SD179	Si-NPN	Sw,Pow,300/300V,40A,580W	53b$	Nec	-
2SD1790	Si-N-Darl+Di	=2SD1788:Int.Z-Diode(B>C),60V	15c	Shi	-
2SD1791	Si-NPN-Darl	Sw,Pow,100V,7A,30W,50MHz,B=1,5k..30k	15c	Shi	2SD1793,(2SD1415,2SD1830,..)
2SD1792	Si-NPN-Darl	=2SD1791:200/200V	15c	Shi	2SD1794
2SD1793	Si-NPN-Darl	Sw,Pow,100V,10A,50W,50MHz,B=1,5k..30k	15c	Shi	(2SD1591,2SD2163)
2SD1794	Si-NPN-Darl	=2SD1793:200V	15c	Shi	(2SD2101)
2SD1795	Si-NPN-Darl	Sw,Pow,500/400V,10A,50W,50MHz,B>150	15c	Shi	-
2SD1796	Si-N-Darl+Di	60V,4A,25W,60MHz,B>2000	17c	Sak	2SD1788,(2SD1987,2SD1825)
2SD1797	Si-NPN-Darl	AF,Sw-Pow,60V,7A,30W,B>800	17c	Fjd	BD645F,2SD1416..17,2SD1791,2SD1826
2SD1798	Si-NPN-Darl	AF,Sw-Pow,300/300V,0,3A,15W,B=5000	17j$	Hit	2SD1502
2SD1799	Si-NPN-Darl	AF,Sw-Pow,30V,3A,15W,120MHz,B>4000	30j$	Sanyo	2SC3132,2SD1222..1223
2SD18	Si-NPN	=2SD15:200/85V	23a$	Sak	BD245F,2SC3263,2SD555,2SD751
2SD180	Si-NPN	AF,Sw-Pow,80V,5A,50W,10MHz	23a$	Nec	BD245B,BD313,2N5758,2SD895..896..
2SD1800	Si-NPN-Darl	AF,Sw-Pow,80V,1,5A,10W,120MHz,B>4000	30j$	Sanyo	2SD1817,2SD1980,2SD2410
2SD1801	Si-NPN	Sw,Pow,Lo-sat,60V,2A,15W,150MHz	30j$	Sanyo	2SC3303,2SD1815..1816
2SD1802	Si-NPN	Sw,Pow,Lo-sat,60V,3A,15W,150MHz	30j$	Sanyo	2SC3303,2SD1815..1816
2SD1803	Si-NPN	Sw,Pow,Lo-sat,60V,5A,20W,180MHz	30j$	Sanyo	2SC3074,2SC3303,2SD1805
2SD1804	Si-NPN	Sw,Pow,Lo-sat,60V,8A,20W,180MHz	30j$	Sanyo	2SC4668
2SD1805	Si-NPN	Sw,Pow,Lo-sat,60V,5A,15W,120MHz	30j$	Sanyo	2SC3074,2SC3303,2SD1803
2SD1806	Si-NPN-Digital+Di	AF,Sw-Pow,40V,2A,15W,150MHz,R2=1ke	30j$	Sanyo	-
2SD1807	Si-NPN	=2SD889:0,3W	40c	Mat	→2SD889
2SD1808(A)	Si-NPN-Darl	=2SD892(A):0,3W	40c	Mat	→2SD892(A)
2SD1809	Si-NPN-Darl	GenP,60V,1A,0,9W,B>2000	7c(9mm)	Rhm	2SD1153,2SD1660,2SD1978,2SD1981..
2SD181	Si-NPN	AF,Sw-Pow,150/100V,15A,100W,10MHz	23a$	Nec	MJ15015,BD745E,BDW12,2SC2607..08..
2SD1810	Si-NPN	AF-Dr/Out,20V,2A,0,5W,80MHz	7c	Rhm	2SC3226,2SD787..88,2SD1100,2SD1207,..
2SD1811	Si-NPN	=2SD1810:SMD	39b	Rhm	2SC2883,2SC2982,2SC3443,2SC3439..
2SD1812	Si-NPN	AF-Dr/Out,160V,1,5A,0,9W,80MHz	7c(9mm)	Rhm	2SC4614,2SD1665A,2SD1857A
2SD1813	Si-NPN	AF,Sw-Pow,70V,4A,25W	15c	Hit	2SC3691,2SC3746,2SC3851,2SD1586..
2SD1814	Si-N-Darl+Di	AF,Sw-Pow,120V,10A,30W,B=5000	15c	Hit	2SD1591,(BDT63C,BDX33D,2SD1607,..)
2SD1815	Si-NPN	Sw,Pow,Lo-sat,120V,3A,20W,180MHz	30j$	Sanyo	-
2SD1816	SI-NPN	Sw;Pow,Lo-sat,120V,4A,20W,180MHz	30j$	Sanyo	-
2SD1817	Si-N-Darl+Di	AF,Sw-Pow,80V,3A,15W,B>2000	30j$	Sanyo	2SD1223,2SD1520,2SD1955
2SD1818	Si-NPN	Lo-sat,60V,3A,10W,120MHz	14h$	Nec	2SD1348
2SD1819	Si-NPN	=2SD601:	35a(2mm)	Mat	BC848W,2SC4081,2SC4128,2SC4155..
2SD1819A	Si-NPN	-	35(2mm)	Mat	→2SD1819A
2SD1819A-Q	Si-NPN	-	35(2mm)	Mat	→2SD1819A
2SD1819A-R	Si-NPN	-	35(2mm)	Mat	→2SD1819A
2SD1819A-S	Si-NPN	-	35(2mm)	Mat	→2SD1819A
2SD181A	Si-NPN	=2SD181:250/200V,10A	23a$	-	BUX17(A..C),BUX42,2SC1586,2SD583,..
2SD182(F)	Si-NPN	AF,Sw-Pow,40V,1A,10W	2a$	Fui	(BD135,BD226,BD507,BD825,..)
2SD1820	Si-NPN	-	35(2mm)	Mat	→2SD1820
2SD1820A	Si-NPN	-	35(2mm)	Mat	→2SD1820A
2SD1820A-Q	Si-NPN	-	35(2mm)	Mat	→2SD1820A
2SD1820A-R	Si-NPN	-	35(2mm)	Mat	→2SD1820A
2SD1820A-S	Si-NPN	-	35(2mm)	Mat	→2SD1820A
2SD1820-Q	Si-NPN	-	35(2mm)	Mat	→2SD1820
2SD1820-R	Si-NPN	-	35(2mm)	Mat	→2SD1820
2SD1820-S	Si-NPN	-	35(2mm)	Mat	→2SD1820
2SD1821	Si-NPN	-	35(2mm)	Mat	→2SD1821
2SD1821A	Si-NPN	-	35(2mm)	Mat	→2SD1821A
2SD1821A-Q	Si-NPN	-	35(2mm)	Mat	→2SD1821A
2SD1821A-R	Si-NPN	-	35(2mm)	Mat	→2SD1821A
2SD1821A-S	Si-NPN	-	35(2mm)	Mat	→2SD1821A
2SD1821A-T	Si-NPN	-	35(2mm)	Mat	→2SD1821A
2SD1821-Q	Si-NPN	-	35(2mm)	Mat	→2SD1821
2SD1821-R	Si-NPN	-	35(2mm)	Mat	→2SD1821
2SD1821-S	Si-NPN	-	35(2mm)	Mat	→2SD1821
2SD1821-T	Si-NPN	-	35(2mm)	Mat	→2SD1821
2SD1822	Si-NPN	AF,25V,0,5A,200MHz	35a(2mm)	Matsushita	BC817W..818W,2SC4118,2SC4097,2SD1820

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2SD1823	Si-NPN	-	35(2mm)	Mat	→2SD1823
2SD1823-R	Si-NPN	-	35(2mm)	Mat	→2SD1823
2SD1823-S	Si-NPN	-	35(2mm)	Mat	→2SD1823
2SD1823-T	Si-NPN	-	35(2mm)	Mat	→2SD1823
2SD1824	Si-NPN	-	35(2mm)	Mat	→2SD1824
2SD1824-R	Si-NPN	-	35(2mm)	Mat	→2SD1824
2SD1824-S	Si-NPN	-	35(2mm)	Mat	→2SD1824
2SD1824-T	Si-NPN	-	35(2mm)	Mat	→2SD1824
2SD1825	Si-N-Darl+Di	AF,Sw-Pow,70V,4A,20W,20MHz,B=5000	17c	Sanyo	2SD1589,2SD1788,2SD1933,2SD2014..
2SD1826	Si-N-Darl+Di	AF,Sw-Pow,70V,7A,25W,20MHz,B=5000	17c	Sanyo	2SD1415..16,2SD1791
2SD1827	Si-N-Darl+Di	AF,Sw-Pow,70V,10A,30W,20MHz,B=5000	17c	Sanyo	BDT63AF,2SD1591,2SD1793,2SD2163
2SD1828	Si-N-Darl+Di	AF,Sw-Pow,110V,3A,20W,20MHz,B=4000	17c	Sanyo	2SD1785,2SD1891..92,2SD2014..15
2SD1829	Si-N-Darl+Di	AF,Sw-Pow,110V,5A,25W,20MHz,B=4000	17c	Sanyo	2SD1315,2SD1336,2SD1785,2SD2025
2SD183(F)	Si-NPN	=2SD182:100V	2a$	Fui	(BD139,BD230,BD529,BD829,..)
2SD1830	Si-N-Darl+Di	AF,Sw-Pow,110V,8A,30W,20MHz,B=4000	17c	Sanyo	BD649F,2SD1590,2SD1773,2SD2025
2SD1831	Si-NPN	Hi-beta,Hi-Ueb,100V,12A,60W,30MHz	16c	Mat	-
2SD1832	Si-NPN	AF,Sw-Pow,80V,5A,30W,8MHz	17c	Rhm	2SC3691,2SC3746,2SD1588,2SD1940
2SD1833	Si-NPN	AF,Sw-Pow,100V,7A,30W,5MHz	17c	Rhm	2SC3692,2SC4550,2SD1411,2SD1588
2SD1834	Si-NPN-Darl	60V,1A,B>2000	39b	Rhm	BST50..52,2SD1470,2SD1511
2SD1835	Si-NPN	Sw,Lo-sat,60V,2A,150MHz,60/580nS	7c	Sanyo	2SC3328,2SD1207,2SD2182,2SD2485
2SD1836	Si-N-Darl+Di	60V,2A,20W,B=4000	17c	Sanyo	2SC3986,2SD1413,2SC1983,2SD2051
2SD1837	Si-N-Darl+Di	50V,3A,20W,20MHz,B=4000	17c	Sanyo	2SC3987,2SD1413,2SD1825,2SD1987
2SD1838	Si-N-Darl+Di	50V,5A,25W,20MHz,B=4000	17c	Sanyo	2SD1790,2SD1796,2SD1825,2SD1987
2SD1839	Si-N-Darl+Di	Sw,Pow,365/365V,5A,80W,B=2000	16c	Mat	-
2SD184	Si-NPN	AF,Sw-Pow,60V,1,5A,25W,-/3,5µS	2a$	Fui	(BD165,BD233,BD239A,BD241A,..)
2SD1840	Si-NPN	AF,Sw-Pow,Lo-sat,110V,15A,100W	18j$	Sanyo	-
2SD1841	Si-NPN	AF,Sw-Pow,Lo-sat,110V,25A,120W	18j$	Sanyo	-
2SD1842	Si-NPN	AF,Sw-Pow,Lo-sat,110V,40A,150W	18j$	Sanyo	-
2SD1843	Si-N-Darl+Di	GenP,Int.Z-Diode,60V,±1A,1W,B>2000	9b	NEC	-
2SD1843A	Si-N-Darl+Di	=2SD1843:80V	9b	-	-
2SD1844	Si-NPN+Diode	TV-HD,1500/700V,1,5A,60W	16c	Mat	BU705DF,2SD1553,2SD1649,(2SD1727,..)
2SD1845	Si-NPN+Diode	TV-HD,1500/700V,2,5A,60W	16c	Mat	BU705DF,BU4505DF,2SD1553,2SD1649,2SD2367..
2SD1846	Si-NPN+Diode	TV-HD,1500/700V,3,5A,60W	16c	Mat	BU706DF,2SD1554,2SD1650,2SD2369..
2SD1847	Si-NPN+Diode	TV-HD,1500/700V,5A,100W	16c	Mat	BU706DF,BU4508DF,2SC4122,2SC4293,2SD1555..
2SD1848	Si-NPN+Diode	TV-HD,1500/700V,6A,100W	16c	Mat	BU508DF,BU4522DF,2SC4122,2SC4294,2SD1556..
2SD1849	Si-NPN+Diode	TV-HD,1500/700V,7A,120W	16c	Mat	BU508DF,BU4523DF,2SC4123,2SC4769,2SC4916..
2SD185	Si-NPN	=2SD184:100V	2a$	Fui	(BD169,BD237,BD239C,BD241C,..)
2SD1850	Si-NPN	TV-HD,1500/700V,7A,120W	16c	Mat	BU508AF,2SC3885A,2SC3895,2SD1547..
2SD1851	Si-NPN	-	35	Sanyo	→2SD1851
2SD1852	Si-NPN-Darl	GenP,80V,0,2A,0,3W,B>5000	40c	Sanyo	MPSA28..29
2SD1853	Si-N-Darl+Di	GenP,80V,1,5A,0,7W,B>2000	7c	Sanyo	2SD1153,2SD1660
2SD1854	Si-N-Darl+Di	=2SD1853:1W	7c(9mm)	Sanyo	2SD1153,2SD1660,2SD1978,2SD1981
2SD1855(A)	Si-NPN	AF-Pow,80V,4A,30W,8MHz	17c	Rhm	2SC3851,2SC3691,2SD1408,2SD2000..
2SD1856	Si-N-Darl+Di	60V,5A,25W,B>2000	17c	Rhm	(2SD1417,2SD1589,2SD1595,2SD1826..)
2SD1857	Si-NPN	=2SD1665(M):Pins=14mm	9c	Rhm	→2SD1665
2SD1858	Si-NPN	=2SD1225(M):Pins=14mm	9c	Rhm	→2SD1225
2SD1859	Si-NPN	=2SD1226(M):Pins=14mm	9c	Rhm	→2SD1226
2SD186	Ge-NPN	AF,25V,0,15A,0,2W	2a	Sanyo	AC127,AC176,AC187,2SD30,2SD72
2SD1860	Si-NPN	=2SD1228(M):Pins=14mm	9c	Rhm	→2SD1228
2SD1861	Si-NPN-Darl	=2SD1536(M):Pins=14mm	9c	Rhm	→2SD1536
2SD1862	Si-NPN	=2SD1227(M):Pins=14mm	9c	Rhm	→2SD1227
2SD1863	Si-NPN	=2SD1768(S):	9c	Rhm	→2SD1768(S)
2SD1864	Si-NPN	=2SD1505:	9c	Rhm	→2SD1507
2SD1865	Si-NPN	=2SD1469M:Pins=14mm	9c	Rhm	→2SD1469M
2SD1866(M)	Si-N-Darl+Di	=2SD1764:1W	9c	Rhm	-
2SD1867(M)	Si-N-Darl+Di	=2SD1660(M):Pins=14mm	9c	Rhm	→2SD1660
2SD1868	Si-NPN	AF/Vid,160/160V,0,1A,0,9W,140MHz	7c(9mm)	Hit	BF391..393,2SC3248,2SC3467..
2SD1869	Si-NPN	=2SD1868:200/200V	7c(9mm)	Hit	BF391..393,2SC3467..3469..
2SD187	Ge-NPN	AF,25V,0,15A,0,2W	2a	Sanyo	AC127,AC176,AC187,2SD30,2SD72
2SD1870	Si-NPN	Hi-beta,30V,1A,B=1k..3k	39b	Hit	2SC3727,2SC5209,2SD1950
2SD1871	Si-NPN	AF,Sw-Pow,40V,2A,10W	30j$	Mit	2SC3076,2SD1078..79,2SD1801..02
2SD1872	Si-NPN	AF,Sw-Pow,60V,1,5A,10W	30j$	Mit	2SD1079,2SD1221,2SD1801..02,2SD1282
2SD1873	Si-NPN	AF,Sw-Pow,110V,0,8A,10W	30j$	Mit	2SC4134,2SD1074..75,2SD1283..84
2SD1874	Si-NPN	AF,Sw-Pow,130V,0,8A,10W	30j$	Mit	2SC2983,2SC4027,2SD1080..82,2SD1220

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2SD1875	Si-N-Darl+Di	AF,Sw-Pow,50V,1,5A,10W,B=10000	14b	Rhm	2SD1509,(BD677,BD777,2SD1376,..)
2SD1876	Si-NPN+Diode	TV-HD,1500/800V,3A,50W	18c	Sanyo	BU706DF,BU4504DX,2SD1553..54,2SD2089..
2SD1877	Si-NPN+Diode	TV-HD,1500/800V,4A,50W	18c	Sanyo	BU706DF,BU4505DX,2SD1554,2SD1650,2SD2089..
2SD1878	Si-NPN+Diode	TV-HD,1500/800V,5A,60W	18c	Sanyo	BU706DF,BU4507DX,2SD1555,2SD2095,2SD2125..
2SD1879	Si-NPN+Diode	TV-HD,1500/800V,6A,60W	18c	Sanyo	BU508DF,BU4508DX,2SC4294,2SD1556,2SD2125..
2SD188(S)	Si-NPN	AF,Sw-Pow,100V,7A(S=(A),60W,10MHz	23a$	Nec	BD245C,BD317,2N5758,2SD895..896..
2SD1880	Si-NPN+Diode	TV-HD,1500/800V,8A,70W	18c	Sanyo	BU508DF,BU4522DX,2SC3893A,2SC4124,2SC4531
2SD1881	Si-NPN+Diode	TV-HD,1500/800V,10A,70W	18c	Sanyo	BU2520DF,BU4525DX,2SC4125,2SC4531,2SC4878
2SD1882	Si-NPN	TV-HD,1500/800V,3A,50W	18c	Sanyo	BU706F,BU4504AX,2SD1544,2SD1654,2SD2381
2SD1883	Si-NPN	TV-HD,1500/800V,4A,50W	18c	Sanyo	BU706F,BU4505AX,2SD1544,2SD1654,2SD2381
2SD1884	Si-NPN	TV-HD,1500/800V,5A,60W	18c	Sanyo	BU706F,BU4507AX,2SC4142,2SD1545,2SD1655..
2SD1885	Si-NPN	TV-HD,1500/800V,6A,60W	18c	Sanyo	BU508AF,BU4508AX,2SC4143,2SD1546,2SD1656..
2SD1886	Si-NPN	TV-HD,1500/800V,8A,70W	18c	Sanyo	BU508AF,BU4522AX,2SC3886A,2SC3896,2SC4758..
2SD1887	Si-NPN	TV-HD,1500/800V,10A,70W	18c	Sanyo	BU2520AF,BU4525AX,2SC3897,2SC4542,2SC4759..
2SD1888	Si-N-Darl+Di	AF,Sw-Pow,120/120V,6A,40W,B=5000	17j$	Rhm	(BD651,BDT21,BDW63D,BDW73D,..)
2SD1889	Si-N-Darl+Di	=2SD1888:Iso,30W	17c	Rhm	2SD1785,2SD2025,2SD1590
2SD189	Si-NPN	AF,Sw-Pow,80V,5A,50W,12MHz	23a$	Mat	BD245B,BDV93,BDX93,2N5632..33..
2SD1890	Si-NPN-Darl	AF,Sw-Pow,100V,3A,35W,20MHz,B>5000	17c	Mat	2SD1315,(2SD1828,2SD2129,2SD2257,..)
2SD1891	Si-NPN-Darl	AF,Sw-Pow,110V,4A,40W,20MHz,B>5000	17c	Mat	2SD1315,(2SD1829,2SD2014)
2SD1892	Si-NPN-Darl	AF,Sw-Pow,120V,5A,45W,20MHz,B>5000	17c	Mat	2SD1315,(2SD1785)
2SD1893	Si-NPN-Darl	AF,Sw-Pow,130V,6A,50W,20MHz,B>5000	16c	Mat	2SD2438
2SD1894	Si-NPN-Darl	AF,Sw-Pow,160V,7A,70W,20MHz,B>5000	16c	Mat	2SD2438
2SD1895	Si-NPN-Darl	AF,Sw-Pow,160V,8A,100W,20MHz,B>5000	16c	Mat	2SD2439
2SD1896	Si-NPN	AF,Sw-Pow,100V,5A,40W,8MHz	17j$	Rhm	BD243C,BD539C,BD953,2SC3258..
2SD1897	Si-NPN	=2SD1896:Iso,30W	17c	Rhm	2SC3691,2SD1407,2SD1588,2SD1940..
2SD1898	Si-NPN	GenP,100V,1A,100MHz	39b	Rhm	BCX56,2SD1005,2SD1386,2SD1418..19
2SD1898-P	Si-NPN	-	39	Rhm	→2SD1898
2SD1898-Q	Si-NPN	-	39	Rhm	→2SD1898
2SD1898-R	Si-NPN	-	39	Rhm	→2SD1898
2SD1899(-Z)	Si-NPN	AF,Sw-Pow,60V,3A,10W,120MHz	30j$	Nec	2SC3386,2SD1221,2SD1802,2SD1815..16..
2SD189A	Si-NPN	=2SD189:100V	23a$	-	BD245C,BDV95,BDX95,2N5632..33..
2SD19	Ge-NPN	AF-Dr/Out,25V,0,3A,0,15W,B=31	2a	Nec	AC127,AC176,AC187,2SD72,2SD352
2SD190	Si-NPN	Sw,Vid-Pow,300V,0,1A,4W,25MHz	?22	Hit	2SC1505..1507,2SC1755..1757,2SC1819,..
2SD1900	Si-NPN-Darl	AF,Sw-Pow,60V,4A,25W,B=5000	15c	Hit	2SD1790,2SD1796,2SD1825,2SD1987..
2SD1901	Si-NPN-Darl	AF,Sw-Pow,60V,8A,25W,B=5000	15c	Hit	2SD1416..17,2SD1793,2SD1826..27..
2SD1902	Si-NPN	AF-Pow,60V,3A,30W,40MHz	30j$	Sanyo	2SD1251..52,(BD241A,BD535,2SC3179..)
2SD1903	Si-NPN	Sw,Pow,Lo-sat,60V,8A,30W,120MHz	30j$	Sanyo	2SD2199,(2SC3254..55)
2SD1904	Si-NPN	Sw,Pow,Lo-sat,60V,5A,30W,30MHz	30j$	Sanyo	2SD1906,2SD2198,2SD2200
2SD1905	Si-NPN	Sw,Pow,Lo-sat,60V,7A,40W,10MHz	30j$	Sanyo	2SD1907,2SD2199,2SD2201
2SD1906	Si-NPN	Sw,Pow,Lo-sat,90V,5A,30W,20MHz	30j$	Sanyo	2SD1907,2SD2200..01
2SD1907	Si-NPN	Sw,Pow,Lo-sat,90V,7A,40W,20MHz	30j$	Sanyo	2SD2201
2SD1908	Si-NPN	TV-HD,330/150V,7A,50W,40MHz	30j$	Sanyo	(BU406..408,2SC3173,2SD884..885,..)
2SD1909	Si-NPN-Darl	AF,Sw-Pow,500/300V,6A,45W,B>500	17c	Mat	2SD1409
2SD191	Ge-NPN	AF,30V,0,15A,0,15W	2a	Tos	AC127,AC176,2SD352
2SD1910..	Si-NPN+Diode	TV-HD,1500/600V,3A,40W	?18c	Hit	BU706DF,2SD1544,2SD1650,2SD2089..
2SD1910FI	Si-NPN+Diode	=2SD1910:	18c	STE	→2SD1910
2SD1911	Si-NPN+Diode	TV-HD,1500/600V,5A,50W	?18c	Hit	BU706DF,2SC4293,2SC4122,2SD1651..
2SD1912	Si-NPN	AF-Pow,60V,3A,30W,100MHz	17j$	Sanyo	2SC3252,(BD241A,BD535,BD539A,..)
2SD1913	Si-NPN	=2SD1912:Iso,20W	17c	Sanyo	2SC3299,2SC3691,2SC3746
2SD1914	Si-N-Darl+Di	Tr-Pow,100V,2A,10W,B=2k..30k	?14h$	Sanyo	(2SD1376,2SD1953)
2SD1915	Si-NPN	Hi-Ueb,(25V),HI-beta,50V,0,3A,B>500	40c	Mat	2SC3615,(2SC3247,2SD1582)
2SD1916	Si-N-Darl+Di	GenP,50V,2A,1W,B=5000	9c	Tos	2SD1153,2SD1809,2SD1866,2SD1853..
2SD1917	Si-N-Darl+Di	60V,1A,B=20000	14b	Mat	-
2SD1918(F5)	Si-NPN	AF,Sw-Pow,160/160V,1,5A,10W,80MHz	30j$	Rhm	2SC2983,2SC4027,2SD1080..82
2SD1919	Si-NPN	=2SD1055:Pins=14mm	9c	Rhm	→2SD1055
2SD192	Ge-NPN	AF,30V,0,15A,0,15W	2a	Tos	AC127,AC176,2SD352
2SD1920	Si-NPN	=2SD1469:Pins=14mm	9c	Rhm	→2SD1469
2SD1921	Si-NPN	=2SD1787:Pins=14mm	9c	Rhm	→2SD1787
2SD1922	Si-NPN+Diode	25V,0,8A,0,9W,B=600	7c(9mm)	Hit	-
2SD1923	Si-N-Darl+Di	AF,Sw-Pow,80V,4A,25W,B=5000	15c	Hit	2SD1589,2SD1928,2SD1933,2SD2014
2SD1924	Si-N-Darl+Di	AF,Sw-Pow,80V,8A,25W,B=5000	15c	Hit	BD645F,2SD1415..16,2SD1793
2SD1925	Si-N-Darl+Di	AF,Sw-Pow,120V,3A,25W,B=5000	15c	Hit	BDT61CF,2SD1785,2SD1892,2SD2014..15
2SD1926	Si-NPN-Darl	AF,Sw-Pow,200/200V,10A,30W,B=5000	15c	Hit	2SD1794,2SD2101,(2SD1756)
2SD1927	Si-N-Darl+Di	AF,Sw-Pow,120/120V,6A,25W,B=5000	15c	Hit	BD649F,2SD1590,2SD1773,2SD1785..

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2SD1928	Si-N-Darl+Di	Sw,Pow,100/100V,±8A,25W,B>2000	17c	Nec	BD647F,2SD1415,2SD1791
2SD1929	Si-N-Darl+Di	60V,2A,1,2W,B=5000	7c(9mm)	Rhm	2SD1854,2SD1931
2SD193	Ge-NPN	AF,35V,0,4A,0,25W,-/4,7μS	2a	Tos	AC127,AC176,2SD352
2SD1930	Si-NPN-Darl	GenP,100V,2A,1,2W,B=5000	7c(9mm)	Rhm	2SD1978,2SD1981
2SD1931	Si-N-Darl+Di	60V,2A,1,2W,B=10000	7c(9mm)	Rhm	-
2SD1932	Si-N-Darl+Di	AF,Sw-Pow,80/80V,4A,35W,B=3000	17j$	Rhm	BD717,BDW32B,BDW53B,BDW63B..
2SD1933	Si-N-Darl+Di	=2SD1932:Iso,30W	17c	Rhm	BD647F,2SD1589,2SD1788,2SD1928..
2SD1934	Si-NPN	=2SD965:1W	7c(9mm)	Mat	2SD966,2SD1244,2SD2249,2SD1961
2SD1935	Si-NPN	-	35	Sanyo	→2SD1935
2SD1936	Si-NPN	AF,Lo-sat,15V,0,8A,0,3W,200MHz	40c	Sanyo	2SD1012,2SD1616,2SD2322
2SD1937	Si-NPN	=2SD1211:	7c(9mm)	Mat	2SC2235,2SD667(A),2SD1616A,2SD1812,..
2SD1938	Si-NPN	=2SD1915:SMD	35a	Mat	-
2SD1938-S	Si-NPN	-	35	Mat	→2SD1938
2SD1938-T	Si-NPN	-	35	Mat	→2SD1938
2SD1939	Si-N-Darl+Di	Sw,150/60V,±1,5A,0,75W,B>2000	7c	Nec	2SD1579,2SD1659,2SD2213
2SD194	Ge-NPN	AF,32V,0,4A,0,25W	2a	Tos	AC127,AC176,2SD352
2SD1940	Si-NPN	AF,Sw-Pow,100V,6A,25W,15MHz	17c	Sanyo	2SC3692,2SC4550,2SD1411,2SD1588..
2SD1941	Si-NPN	TV-HD,1500/650V,6A,50W	?18c	Hit	BUS08AF,2SC4143,2SD1546,2SD1656..
2SD1942	Si-NPN	AF,40V,2A,1,2W	7c(9mm)	Rhm	2SC3328,2SC4145,2SD1146,2SD1207..
2SD1943	Si-NPN	Hi-beta,80V,3A,40W,50MHz,B>400	17j$	Rhm	(2SD1157,2SC1983)
2SD1944	Si-NPN	=2SD1943:Iso,30W	17c	Rhm	2SD1273,2SD2092,2SD2156,2SD2375,..
2SD1945	Si-NPN	AF,Sw-Pow,1000/1000V,0,5A,20W	30j$	Hit	BUD87
2SD1946	Si-NPN	Hi-beta,15V,1A,B=800	39b	Hit	2SC3439,2SC4390,2SD1870
2SD1947(A)	Si-NPN+Diode	Hi-beta,Lo-sat,100V,10A,70MHz,B>500	17c	Tos	2SC4024
2SD1948	Si-NPN+Diode	Hi-beta,lo-sat,60V,5A,110MHz,B>500	17c	Tos	2SD2075..2076
2SD1949	Si-NPN	=2SD1484K:	35a(2mm)	Rhm	PMST4401
2SD1949K-P	Si-NPN	-	35(2mm)	Rhm	→2SD1949K
2SD1949K-Q	Si-NPN	-	35(2mm)	Rhm	→2SD1949K
2SD1949K-R	Si-NPN	-	35(2mm)	Rhm	→2SD1949K
2SD195	Ge-NPN	AF,Sw,20V,0,05A,0,15W	2a	Fui	AC127,2SD30
2SD1950	Si-NPN	Hi-beta,Hi-Ueb,30V,2A,B=1500	39b	Nec	-
2SD1950-VK	Si-NPN	-	39	Nec	→2SD1950
2SD1950-VL	Si-NPN	-	39	Nec	→2SD1950
2SD1950-VM	Si-NPN	-	39	Nec	→2SD1950
2SD1951	Si-NPN	GenP,Lo-sat,20V,3A,0,75W,140MHz	7c	Nec	2SC4487,2SD879,2SD1617,2SD1347
2SD1952	Si-NPN	=2SD1951:SMD	39b	Nec	2SD1119,2SD1620,2SD1624
2SD1953	Si-N-Darl+Di	AF,Sw-Pow,120V,1,5A,10W,B=8000	14h$	Sanyo	2SD1376
2SD1955	Si-N-Darl+Di	AF,Sw-Pow,110V,3A,10W,20MHz,B>1500	30j$	Sanyo	2SC4339
2SD1956	Si-NPN+Diode	AF,Sw-Pow,120V,7A,40W,40MHz,B=300	17j$	Rhm	-
2SD1957	Si-NPN+Diode	=2SD1956:Iso,30W	17c	Rhm	-
2SD1958	Si-NPN	TV-HD,Sw,Pow,200/60V,4,5A,30W,10MHz	17c	Sanyo	(2SC4153)
2SD1959	Si-NPN	Sw,Pow,TV-HD,1400/650V,10A,50W	18c	Sanyo	BU2520AF,2SC3897,2SC4542,2SD1548..
2SD196(A)	Si-NPN	AF,Sw-Pow,100/50V,10A,125W(A=150W)	38a$	Fui	(BD249C,BD745C,2SD1049)
2SD1960	Si-NPN	AF,Lo-sat,30V,5A,0,75W,170MHz	7c	Rhm	2SC4482,2SD1145
2SD1961	Si-NPN	AF,Strobo,50V,5A,1,2W,150MHz	7c(9mm)	Rhm	2SC3671,2SC4482,2SD1145,2SD2097..
2SD1962(M)	Si-NPN	=2SD1961:0,3W,M=1W	9c	Rhm	2SC3671,2SC4482,2SD1145,2SD2097..
2SD1963	Si-NPN	Strobo,50V,3A,150MHz	39b	Rhm	2SC4521,2SD1624
2SD1963-Q	Si-NPN	-	39	Rhm	→2SD1963
2SD1963-R	Si-NPN	-	39	Rhm	→2SD1963
2SD1963-S	Si-NPN	-	39	Rhm	→2SD1963
2SD1964	Si-NPN	AF,Sw-Pow,130/80V,15A,50W,20MHz	17c	Mat	2SC3699
2SD1965	Si-NPN	AF,Sw-Pow,120V,1A,5W	?14b	Rhm	2SD1684
2SD1966	Si-NPN	AF,Sw-Pow,80V,0,7A,5W	?14b	Rhm	2SD1200
2SD1967	Si-NPN-Darl	AF,Sw-Pow,40V,2A,5W,B=20000	?14b($)	Rhm	2SD947
2SD1968	Si-NPN	AF,Sw-Pow,40V,2A,5W	14b	Rhm	2SC3422,2SD1189,2SD1682
2SD1969	Si-NPN	50V,2A,0,5W	62b	Rhm	-
2SD197(A)	Si-NPN	=2SD196:130/70V	38a$	Fui	(2SD1049)
2SD1970	Si-N-Darl+Di	24V,2A,10W,B>7000	14h$	Hit	2SD947,2SD1509
2SD1971	Si-NPN	Sw,Pow,400/400V,0,5A,5W,55MHz	14h$	Mat	2SC2752,2SC2899,2SC3051
2SD1972	Si-NPN	Lo-sat,60V,3A,15W,100MHz,Hi-B>250	17c	Mit	2SD2092,2SD2127,2SD1948
2SD1973	Si-NPN	Hi-beta,80V,2A,B=1000	14b	Mat	-
2SD1974	Si-NPN+Diode	-	39	Hit	→2SD1974
2SD1975	Si-NPN	AF,Sw-Pow,180V,15A,150W,20MHz	77j$	Mat	2SC3281,2SD1704,2SD1718,2SD2155
2SD1976	Si-N-Darl+Di	300/300V,6A,40W,B>500	17j$	Hit	2SD991,2SD1071,2SD1088,2SD1113..

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2SD1977	Si-NPN	AF,Sw-Pow,120V,8A,65W,60MHz	18c	Nec	2SC4386,2SC4689,(BD245C,BD545D,..)
2SD1978	Si-N-Darl+Di	AF,120V,1,5A,0,9W,B=2k..30k	7c(9mm)	Hit	2SD1579,2SD1659,2SD2067,2SD2213
2SD1979	Si-NPN	-	35(2mm)	Mat	→2SD1979
2SD1979-S	Si-NPN	-	35(2mm)	Mat	→2SD1979
2SD1979-T	Si-NPN	-	35(2mm)	Mat	→2SD1979
2SD198(Z)	Si-NPN	Sw,Pow,300V,1A,25W(Tc=75°),45(Z=25)MHz	23a$	Matsushita	BU126,2SC2809,2SD632
2SD1980(FS)	Si-N-Darl+Di	AF,Sw-Pow,100V,2A,10W,B=3000	30j$	Rhm	2SD1223,2SD1520,2SD2410
2SD1981	Si-N-Darl+Di	AF,100V,2A,1W,B=7000	7c(9mm)	Sanyo	2SC1879,2SD1660,2SD1867,2SD1978
2SD1982	Si-N-Darl+Di	Sw,Pow,300/300V,6A,80W,B=2000	18j$	Hit	2SD1461
2SD1983	Si-N-Darl+Di	60V,1,5A,20W,B=10000	17c	Rhm	2SD2051
2SD1984	Si-NPN	AF,Hi-beta,30V,1A,0,9W,B=1500	7c(9mm)	Hit	2SC3070,2SC3225,2SC3726
2SD1985(A)	Si-NPN	=2SD1252(A):25W	17c	Mat	BD935F,2SC3851..52,2SD1585,2SD1913
2SD1986	Si-NPN-Darl	AF,Sw-Pow,60V,4A,35W,B=5000	17j$	Rhm	BD715,BDW23A,BDW53A,BDW63A..
2SD1987	Si-NPN-Darl	=2SD1986:Iso,30W	17c	Rhm	2SD1595,2SD1790,2SD1796,2SD1933..
2SD1988	Si-N-Darl+Di	45V,2A,25W,B=3000	17j$	Rhm	BD713,BDW53,2SD837..
2SD1989	Si-N-Darl+Di	=2SD1988:Iso,20W	17c	Rhm	BDT61F,2SC3986,2SD1796,2SD1987..
2SD199	Si-NPN	Sw,Pow,800V,0,25A,25W(Tc=75°),7MHz	23a$	Matsushita	2SC3151
2SD1990	Si-NPN	AF,Sw-Pow,80V,4A,35W,80MHz	17j$	Mat	BDV10..12,2SC3253,2SC3258
2SD1991	Si-NPN	=2SD636:Pins=14mm	9c	Mat	→2SD636
2SD1991A	Si-NPN	=2SD637:Pins=14mm	9c	-	→2SD637
2SD1992	Si-NPN	→2SD938:Pins=14mm	9c	Rhm	→2SD638
2SD1992A	Si-NPN	→2SD939:Pins=14mm	9c	-	→2SD639
2SD1993	Si-NPN	=2SD661A:Pins=14mm	9c	Mat	→2SD661A
2SD1994(A)	Si-NPN	=2SD973(A):Pins=14mm	9c	Mat	→2SD973(A)
2SD1995	Si-NPN	=2SD1010:Pins=14mm	9c	Mat	→2SD1010
2SD1996	Si-NPN	=2SD1302:Pins=14mm	9c	Mat	→2SD1302
2SD1997	Si-NPN-Digital+Di	Motor-Dr,40V,3A,R1=160Ω,R2=800Ω	39b	Sanyo	-
2SD1998	Si-NPN-Digital+Di	Motor-Dr,40V,3A,R1=0Ω,R2=800Ω	39b	Sanyo	-
2SD1999	Si-NPN-Digital+Di	Motor-Dr,30V,4A,R1=0Ω,R2=1,5kΩ	39b	Sanyo	-
2SD20	Ge-NPN	=2SD19:B=50	2a	Nec	AC127,AC176,AC187,2SD72,2SD352
2SD200(A)	Si-NPN	TV-HD,1500V,2,5A,10W(Tc=90°)	23a$	Matsushita	BU205..206,2SC1922,BU705,2SD818..
2SD2000	Si-NPN	=2SD1990:Iso	17c	Mat	2SC3691,2SC3746,2SC4549,2SC4596
2SD2001	Si-NPN+Diode	Sw,Pow,TV-HD,1500/700V,1,5A,40W	17c	Mat	BU505DF
2SD2002	Si-NPN	Sw,Pow,TV-HD,1500/800V,5A,50W	18c	Sanyo	BU508AF,2SC3894,2SC4142,2SD1884..
2SD2004	Si-NPN	GenP,160/160V,1,5A,1,2W,80MHz	78b	Rhm	2SC2983,2SC4027,2SD1918,2SA2122..23
2SD2005	Si-NPN	Lo-sat,40V,1A,1,2W,150MHz	78b	Rhm	2SC3076,2SD1801
2SD2006	Si-NPN	Lo-sat,80V,0,7A,1,2W,120MHz	78b	Rhm	-
2SD2007	Si-NPN	Lo-sat,40V,2A,1,2W,100MHz	78b	Rhm	2SC3076,2SD1801
2SD2008	Si-NPN	Lo-sat,120/80V,1A,1,2W,100MHz	78b	Rhm	2SC4135
2SD2009	Si-NPN-Darl	AF,60/60V,1A,1,2W,B>2000	78b	Rhm	2SC2871,2SC4500,2SD1598,2SD1800
2SD201	Si-NPN	AF,Sw-Pow,90/60V,6A,50W,-/4μS	23a$	Sak	BD245C,BDV95,BDX95,2N5632..33..
2SD2010	Si-N-Darl+Di	60/60V,2A,1,2W,B>1000	78b	Rhm	-
2SD2011	Si-N-Darl+Di	=2SD1638:	78b	Rhm	2SD1955,2SD1980,2SD2410
2SD2012	Si-NPN	AF-Pow,60V,3A,25W,3MHz,B=100..320	17c	Tos	BD935F,2SD1406,2SD1585,2SD1913..
2SD2014	Si-N-Darl+Di	AF,Sw-Pow,120/80V,4A,25W,75MHz,B>2000	17c	Sak	BDT61C,2SD1336,2SD1785
2SD2015	Si-N-Darl+Di	AF,Sw-Pow,150/120V,4A,25W,40MHz,B>2000	17c	Sak	2SD1590,2SD1789
2SD2016	Si-N-Darl+Di	AF,Sw-Pow,250/200V,3A,25W,90MHz,B>1000	17c	Sak	-
2SD2017	Si-N-Darl+Di	Sw,Pow,300/250V,6A,35W,B>2000	17c	Sak	2SD1410,(2SD1088,2SD1113,2SD1976,..)
2SD2018	Si-N-Darl+Di	1A,5W,150MHz,B>6500	14b	Mat	-
2SD2019	Si-N-Darl+Di	AF-Pow,150V,1,5A,10W,B>5000	14h$	Hit	2SC4342,2SD985..986
2SD202	Si-NPN	=2SD201:110/80V	23a$	Sak	BD245C,2N5633,2SC2681,2SD718..
2SD2020	Si-NPN	AF,Sw-Pow,150V,2A,40W	17j$	Rhm	BD239D,2SC1669,2SC2073,2SD1138..
2SD2021	Si-NPN	=2SD2020:Iso,30W	17c	Rhm	BDT31DF,2SC3567,2SC3695,2SD1587
2SD2022	Si-N-Darl+Di	60V,1,5A,25W,B=3000	17j$	Rhm	BD715,BDW23A,BDW53A,BDW63A..
2SD2023	Si-NPN	AF,Sw-Pow,80V,3A,40W,8MHz	17j$	Rhm	BD241B,BD537,BD951,2SC3179..
2SD2024	Si-N-Darl+Di	AF,Sw-Pow,100V,8A,40W,B=10000	17j$	Rhm	-
2SD2025	Si-N-Darl+Di	=2SD2024:Iso,30W	17c	Rhm	-
2SD2026	Si-NPN-Darl	30V,0,3A,200MHz,B=30000	35a	Rhm	2SD1478
2SD2027	Si-NPN	AF,Sw-Pow,60V,3A,30W,8MHz	17j$	Sanyo	BD241A,BD535,BD935,2SC3179..
2SD2028	Si-NPN+Diode	8V,0,7A	35a	Sanyo	-
2SD2029	Si-NPN	Sw,Pow,160/160V,12A,120W,20MHz	77j$	Mat	2SC3280..81,2SD1717..18,2SD1975..
2SD203	Si-NPN	=2SD201:130/100V	23a$	Sak	BD245D,BDX11,2N4348,2N5634,2SD551,..
2SD2030	Si-NPN	=2SD1868:0,4W	7c	Hit	BF420A,BF422A,BF391,2SC3248..
2SD2031	Si-NPN	=2SD1869:0,4W	7c	Hit	BF420A,BF422A,BF391,2SC3467..

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2SD2032	Si-N-Darl+Di	AF, Sw-Pow, 80V, 4A, 20W, B=3000	78c	Rhm	(2SD1223, 2SD1520)
2SD2033	Si-NPN	AF, Sw-Pow, 120V, 1,5A, 1,8W, 80MHz	78c	Rhm	(2SC2690, 2SD1563, 2SD1684)
2SD2033A	Si-NPN	=2SD2033: 160V	78c	Rhm	(2SC2690A, 2SC3117, 2SD1563A)
2SD2034	Si-NPN	AF, Sw-Pow, 80V, 3A, 25W	78c	Rhm	(BD441, BD787, BD789, MJE240..242)
2SD2035	Si-NPN	AF, Sw-Pow, 80V, 4A, 1,8W, 8MHz	78c	Rhm	(BD441, BD787, BD789, MJE240..242)
2SD2036	Si-NPN	AF, Sw-Pow, 100V, 7A, 1,8W, 5MHz	78c	Rhm	-
2SD2037	Si-NPN	AF, Sw-Pow, 60V, 3A, 1,8W, 90MHz	78c	Rhm	(BD787, BD789, 2SD1506, 2SD1818,..)
2SD2038	Si-NPN	AF, Sw-Pow, 80V, 5A, 1,8W, 8MHz	78c	Rhm	-
2SD2039	Si-N-Darl+Di	AF, Sw-Pow, 100V, 2A, 1,8W, B=4000	78c	Rhm	(2SD985..86, 2SD1376, 2SD1953)
2SD204	Si-NPN	AF, Sw-Pow, 60V, 0,7A, 0,7W, 9W(Tc=25°)	2a	Nec	(BD137, BD228, BD517, BD525,..)
2SD2040	Si-NPN	AF, Sw-Pow, 100V, 5A, 1,8W, 8MHz	78c	Rhm	-
2SD2041	Si-N-Darl+Di	60V, 2A, B=4000	78c	Rhm	-
2SD2042	Si-N-Darl+Di	60V, 5A, B=10000	78c	Rhm	-
2SD2043	Si-N-Darl+Di	AF, Sw-Pow, 120V, 6A, B=10000	78c	Rhm	-
2SD2044	Si-NPN	AF, Sw-Pow, Hi-beta, 80V, 3A, B=400..2000	78c	Rhm	-
2SD2045	Si-N-Darl+Di	AF, Sw-Pow, 120V, 6A, 50W, 50MHz, B>2000	18c	Sak	2SD1893, 2SD2437, (2SD1170, 2SD1210)
2SD2046	Si-N-Darl+Di	50V, 1,5A, 1W, B=2k..10k	7c(9mm)	Hit	2SD1809, 2SD1866, 2SD1929, 2SD1931..
2SD2047(R)	Si-NPN	Sw, Pow, TV-HD, 1500V, 5A, 80W	18c	Fjd	BU2508AF, 2SC3894, 2SD1545, 2SD1655..
2SD2048	Si-N-Darl+Di	AF, Sw-Pow, 110V, 3A, 30W, 20MHz, B=4000	30j$	Sanyo	-
2SD2049	Si-N-Darl+Di	AF, Sw-Pow, 110V, 5A, 35W, 20MHz, B=4000	30j$	Sanyo	-
2SD205	Si-NPN	AF, Sw-Pow, 60V, 0,7A, 9W(Tc=25°)	2a$	Nec	(BD137, BD228, BD517, BD525,..)
2SD2050	Si-N-Darl+Di	AF, Sw-Pow, 110V, 8A, 40W, 20MHz, B=4000	30j$	Sanyo	-
2SD2051	Si-N-Darl+Di	60V, 1,6A, 12W, >200MHz, B>4000	17c	Mat	2SD1983
2SD2052	Si-NPN	AF, Sw-Pow, 150/150V, 9A, 100W, 20MHz	16c	Mat	2SC4386, 2SC5100, (BD245D, 2SD1046,..)
2SD2053	Si-NPN	=2SD2052:	18j$	Mat	BD245D, 2SC2837, 2SC3907, 2SD1046..
2SD2054	Si-NPN	AF, 100V, 1A	39b	Hit	BCX56, 2SD1005, 2SD1368, 2SD1418..19,..
2SD2055	Si-NPN	AF, Sw-Pow, 80V, 10A, 40W	17j$	Rhm	BD709, BD743B, BD809, BD909..
2SD2056	Si-NPN	=2SD2055: Iso, 30W	17c	Rhm	BDT95F, 2SC3693..3694
2SD2057	Si-NPN+Diode	Sw, Pow, TV-HD, 1500/700V, 5A, 100W	16c	Mat	BU508DF, BU4523DF, 2SC4122, 2SC4293, 2SD1555..
2SD2058	Si-NPN	AF, Sw-Pow, 60V, 3A, 25W, 3MHz, <0,8/2,3µS	17c	Kec	2SC3851..52, 2SD1585, 2SD1985, 2SD2012..
2SD2059	Si-NPN	AF, Sw-Pow, 100V, 5A, 30W, 12MHz	17c	Kec	BD953F, 2SC3540, 2SC3691, 2SD1940..
2SD206(A)	Si-NPN	AF, Sw-Pow, 50/30V, 10A, 150W	23a$	Shi	BD315, 2N5629..31, 2SC2608, 2SD1105..
2SD2060	Si-NPN	AF, Sw-Pow, 80V, 4A, 25W, 8MHz	17c	Kec	BD951F, 2SC3691, 2SC3851, 2SD2000..
2SD2061	Si-NPN	=2SD2023: Iso, 30W	17c	Rhm	2SC3690, 2SC3852, 2SD1761, 2SD2394..
2SD2062	Si-NPN	AF, Sw-Pow, 100/80V, 7A, 80W, 8MHz	16c(j$)	Rhm	2SC4385, 2SD2064, (BD245C, 2SC2681,..)
2SD2063	Si-NPN	AF, Hi-beta, 15V, 1A, 0,9W, B=700	7c(9mm)	Hit	2SC3070, 2SC3225, 2SC3726, 2SD1984
2SD2064	Si-NPN	AF, Sw-Pow, 120/120V, 6A, 70W, 20MHz	16c	Mat	2SC4385, 2SC5099, (BD245D, 2SC4486,..)
2SD2065	Si-NPN	AF, Sw-Pow, 140/140V, 7A, 80W, 20MHz	16c	Mat	2SC4386, 2SC5100, (BD245D, 2SC4467,..)
2SD2066	Si-NPN	AF, Sw-Pow, 160/160V, 12A, 120W, 20MHz	18j$	Mat	BD745E, 2SC2987A, 2SC3907, 2SD1047,..
2SD2067	Si-N-Darl+Di	GenP, 120/100V, 2A, 1W, B>4k	9c	Mat	2SD1579, 2SD1659, 2SD1978
2SD2068	Si-N-Darl+Di	GenP, Int. Z-Di, 60V, 1A, 1W, B>4000	7c(9mm)	Mat	2SD1809, 2SD1866, 2SD1929, 2SD1931..
2SD2069	Si-NPN	Lo-sat, 60V, 2A, 1W, 210MHz	7c(9mm)	Rhm	2SC3328, 2SC4486, 2SD1207, 2SD2177
2SD207(A)	Si-NPN	=2SD206: 100/60V	23a$	Shi	BD317, 2N5629..31, 2SC2608, 2SD1105..
2SD2070	Si-NPN	GenP, 50V, 0,1A, 1W	9c	Mat	BC174, BC182, BC190, BC546, 2SD767..
2SD2071	Si-NPN	GenP, 50V, 0,5A, 1W, 200MHz	9c	Mat	BC337..338, BC635, BC637, 2SD1226..
2SD2072	Si-NPN	=2SD661: 1W, Pins=14mm	9c	Mat	→2SD661
2SD2073	Si-NPN	=2SD1010: 1W	9c	Mat	→2SD1010
2SD2074	Si-NPN	=2SD1302: 1W	9c	Mat	→2SD1302
2SD2075(A)	Si-NPN+Diode	Hi-beta, Lo-sat, 60V, 10A, 90MHz, B>500	17c	Tos	2SD1947
2SD2076	Si-NPN+Diode	Hi-beta, Lo-sat, 100V, 5A, 90MHz, B>500	17c	Tos	2SC4553, 2SD1947
2SD2079	Si-N-Darl+Di	AF, Sw-Pow, 100V, 5A, 30W, B=2k..15k	17c	Tos	BD647F, 2SD1589, 2SD1829..30, 2SD1785..
2SD208(A)	Si-NPN	=2SD206: 150/90V	23a$	Shi	BDW12, MJ15015, 2N3773, 2SC2607..08,..
2SD2081	Si-N-Darl+Di	AF, Sw-Pow, 120/120V, 10A, 30W, B>2000	17c	Sak	BDT63CF, BDT65CF, 2SD1591
2SD2082	Si-N-Darl+Di	AF, Sw-Pow, 120/120V, 16A, 75W, B>2000	18c	Sak	BDV67BF
2SD2083	Si-N-Darl+Di	AF, Sw-Pow, 120/120V, 25A, 120W, B>2000	18j$	Sak	2SD1597, 2SD2256
2SD2084	Si-NPN-Darl	Sw, Pow, 450/450V, 6A, 50W, B>1000	17j$	-	BU810, BU911..912, 2SD798..799..
2SD2085	Si-NPN	Hi-beta, 80V, 6A, 40W, 50MHz, B>400	17j$	Rhm	(2SC2315..16, 2SC2491)
2SD2088	Si-N-Darl+Di	60V, 2A, 0,9W, 100MHz, B>2000	7c(9mm)	Tos	2SD1153, 2SD1809, 2SD1854, 2SD1929..
2SD2089	Si-NPN+Diode	CTV-HD, 1500/600V, 3,5A, 40W	18c	Tos	BU2508DF, BU4504DX, 2SD1554, 2SD1650, 2SD1877..
2SD209..210	Si-NPN	-		Shi	-
2SD2090	Si-N-Darl+Di	90V, 2A, 25W, B>1000	17j$	Rhm	-
2SD2091	Si-N-Darl+Di	=2SD2090: Iso	17c	Rhm	-
2SD2092	Si-NPN+Diode	Hi-beta, Lo-sat, 100V, 3A, 140MHz, B>500	17c	Tos	2SD2076
2SD2093	Si-N-Darl+Di	110V, 10A, 45W, 20MHz, B=4000	?18c	Sanyo	BDV65CF, (BDW83D, 2SD1230,..)

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2SD2094	Si-N-Darl+Di	AF-Pow,120/120V,8A,25W,B>1000	17c	Hit	BD649F,2SD1773
2SD2095	Si-NPN+Diode	CTV-HD,1500/600V,5A,50W	18c	Tos	BU508DF,BU4507DX,2SD1555,2SD1651,2SD2125..
2SD2096	Si-NPN	=2SD2023:1,8W	78c	Rhm	(BD441,BD787,BD789,MJE240..241)
2SD2097	Si-NPN	=2SD1961:Pins=14mm	9c	Rhm	2SC3671,2SC4482,2SD1145
2SD2098	Si-NPN	=2SD1961:SMD	39b	Rhm	2SD1628
2SD2098-Q	Si-NPN	-	39	Rhm	→2SD2098
2SD2098-R	Si-NPN	-	39	Rhm	→2SD2098
2SD2098-S	Si-NPN	-	39	Rhm	→2SD2098
2SD2099	Si-NPN-Digital+Di	Motor-Dr,Io-sat,40V,3A,R1=90Ω,R2=800Ω	39b	Sanyo	-
2SD21	Ge-NPN	=2SD19:B=72	2a	Nec	AC127,AC176,AC187,2SD72,2SD352
2SD2100	Si-NPN-Digital+Di	Lo-sat,25V,2A,R1=0,R2=1,6kΩ	39b	Sanyo	-
2SD2101	Si-NPN-Darl	AF-Pow,200/200V,10A,30W,B>1500	17c	Hit	2SD1794
2SD2102	Si-NPN-Darl	AF-Pow,60V,4A,25W,B>1000	17c	Hit	BDT61(A,B,C)F,2SD1595,2SD2131..
2SD2103	Si-NPN-Darl	AF-Pow,60V,8A,25W,B>1000	17c	Hit	BD643F,2SD1415..17,2SD1826..27..
2SD2104	Si-N-Darl+Di	AF-Pow,120/120V,8A,25W,B>1000	17c	Hit	BD649F,BD651F,2SD1590,2SD1773
2SD2105	Si-N-Darl+Di	AF-Pow,120/120V,10A,30W,B>1000	17c	Hit	BDT63CF,2SD1591,2SD2081
2SD2106	Si-N-Darl+Di	AF-Pow,120/120V,6A,25W,B>1000	17c	Hit	BD649F,BD651F,2SD1336,2SD1590
2SD2107	Si-NPN	AF-Pow,70V,4A,25W	17c	Hit	BD951F,BD953F,BD955F,2SD1407
2SD2108	Si-N-Darl+Di	AF-Pow,80V,8A,25W,B>1000	17c	Hit	BD645F,BD647F,2SD1415..16..
2SD2109	Si-NPN-Darl	Sw,Pow,300/300V,0,3A,15W,B>1000	17c	Hit	2SD2217,(2SD1502,2SD1798)
2SD211	Si-NPN	AF,Sw-Pow,60/40V,10A,100W,-/4,4µS	23a$	Sak	BD311,BDW21A,2N3055,2N5877..78..
2SD2110	Si-N-Darl+Di	AF-Pow,80V,4A,25W,B>1000	17c	Hit	BDT61(A..C)F,2SD1933,2SD2014..
2SD2111	Si-N-Darl+Di	AF-Pow,120/120V,3A,25W,B>1000	17c	Hit	BDT61CF,2SD2014..15
2SD2112	Si-N-Darl+Di	AF-Pow,120/120V,6A,25W,B>1000	17c	Hit	BD649F,BD651F,2SD1336
2SD2113	Si-N-Darl+Di	AF-Pow,120/120V,3A,25W,B>1000	17c	Hit	BDT61CF,2SD2014..15
2SD2114K	Si-NPN	=2SD2132:SMD	35a	Rhm	-
2SD2114K-U	Si-NPN	-	35	Rhm	→2SD2114K
2SD2114K-V	Si-NPN	-	35	Rhm	→2SD2114K
2SD2114K-W	Si-NPN	-	35	Rhm	→2SD2114K
2SD2115L,S	Si-NPN	AF-Pow,150/60V,2A,18W	30j$	Hit	2SD1033,2SD1557
2SD2116	Si-NPN-Darl	GenP,80V,0,7A,1W,200MHz,B>5000	9c	Sanyo	BC618,BC877,BC879,2SD1153..
2SD2117	Si-NPN-Darl	GenP,80V,1,5A,1W,B>4000	9c	Sanyo	2SD1153,2SD1660,2SD1853..54,2SD1981,+
2SD2118(FS)	Si-NPN	AF,Strobo,50V,5A,10W,150MHz	30j$	Rhm	2SC3072,2SC3074,2SD1803,2SD1805..
2SD2119	Si-NPN-Darl	AF-Pow,90V,4A,25W,B>2000	17c	Rhm	BDT61BF..CF,2SD1414,2SD1788,2SD2079+
2SD212	Si-NPN	=2SD211:90/60V	23a$	Sak	BD313,BDW21C,2N3055,2N5632..33..
2SD2120	Si-N-Darl+Di	GenP,100V,2A,1W,B=2k..30k	9c	Sanyo	2SD1660,2SD1981
2SD2121L,S	Si-NPN	AF-Pow,35V,2,5A,18W	30j$	Hit	2SC3386,2SD1221,2SD1760,2SD1802..
2SD2122L,S	Si-NPN	AF-Pow,180/120V,1,5A,18W,180MHz	30j$	Hit	2SC4027,2SD1080..82
2SD2123L,S	Si-NPN	AF-Pow,180/160V,1,5A,18W,180MHz	30j$	Hit	2SC4027,2SD1080..82
2SD2124L,S	Si-N-Darl+Di	AF-Pow,120/120V,1,5A,18W,B>2000	30j$	Hit	2SD1464..65
2SD2125	Si-NPN+Diode	CTV-HD,1500/600V,6A,50W	18c	Tos	BU508DF,BU4508DX,2SC4294,2SD1556,2SD1652..
2SD2127	Si-NPN+Diode	Hi-beta,Lo-sat,60V,3A,140MHz,B>500	17c	Tos	2SD1948,2SD1972,2SD2076
2SD2128	Si-N-Darl+Di	AF-Pow,60V,3A,25W,B>1000	17c	Hit	BDT61(A..C)F,2SD1413,2SD1796..
2SD2129	Si-N-Darl+Di	Sw,Pow,100V,3A,20W,B=2000..15000	17c	Tos	2SD1414,2SD1788,2SD1828,2SD2014..
2SD213	Si-NPN	=2SD211:110/80V	23a$	Sak	BDW21C,2N3055,2N5632..33,2SD551..
2SD2130	Si-N-Darl+Di	60V,±4A,10W,60MHz,B=2000..15000	14b	Tos	2SD1796
2SD2131	Si-N-Darl+Di	60V,5A,30W,B=2000..15000	17c	Tos	2SD1595
2SD2132	Si-NPN	Lo-sat,Hi-beta,25V,Ueb=12V,0,5A,B>560	7c	Rhm	2SC4204,2SD2144..45,2SD2191..92
2SD2133	Si-NPN	AF-Pow,60V,1A,1,5W,200MHz	78b	Mat	(BD137,BD139,BD228,BD377,..)
2SD2134	Si-NPN	AF-Out,180/180V,1A,1,5W,200MHz	78b	Mat	(2SC3117,2SC3902,2SD669)
2SD2135	Si-N-Darl+Di	60V,1A,150MHz,B>6500	78b	Mat	-
2SD2136	Si-NPN	AF-Out/Sw,60V,3A,1,5W,500/2900nS	78b	Mat	(BD785,2SD794(A),2SD1506,2SD1818)
2SD2137	Si-NPN	AF-Out/Sw,60V,3A,15W,30MHz	78c	Mat	(2SD1406,2SD1585,2SD1985,2SD1913,..)
2SD2137A	Si-NPN	=2SD2137:80V	78c	-	(BDT31F,2SC3690,2SD1761,2SD2061,..)
2SD2138	Si-N-Darl+Di	AF-Pow,60V,2A,15W,20MHz,B>1000	78c	Mat	(BDT61(A..C)F,2SD1413,2SD1983,..)
2SD2138A	Si-N-Darl+Di	=2SD2138:80V	78c	-	(BDT61A..CF,2SC2399,2SD1414,2SD1933)
2SD2139	Si-NPN	Hi-beta,80V,3A,15W,50MHz,B>500	78c	Mat	(2SD1273,2SD2156,2SD2375,2SD2396,..)
2SD214	Si-NPN	=2SD211:130/100V	23a$	Sak	BDX11,2N3442,2SD551,2SD732..733..
2SD2140	Si-NPN	AF-Out,140/140V,7A,80W,20MHz	18j$	Mat	BD245D,2SC2706,2SC2837,2SC3182..
2SD2141	Si-N-Darl+DI	Sw,Pow,+Z-DI,380V,6A,35W,B>1500	17c	Sak	-
2SD2142K	Si-NPN-Darl	GenP,40V,0,3A,200MHz,B>5000	35	Rhm	BCV27,BCV47,2SD1383K,2SD1478A
2SD2143	Si-N-Darl+Di	60±10V,2A,10W,B>1000	30j$	Rhm	2SC4338,2SD1222,2SD1817
2SD2144(S)	Si-NPN	=2SD2132:0,3W	41c	Rhm	→2SD2132
2SD2145(M)	Si-NPN	=2SD2132:0,4W	9c	Rhm	→2SD2132

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2SD2146	Si-NPN	AF,60V,3A,1,2W,90MHz	78b	Rhm	2SC3386,2SC4522,2SD1802,2SD1221,..
2SD2147	Si-NPN	Strobo Flash,AF,50V,5A,150MHz	14h$	Rhm	2SC2270,2SD826
2SD2148	Si-NPN	Sw,Pow,HD,1500/700V,8A,50W	?18c	Hit	BU508AF,2SC3886A,2SC3896,2SC4758..
2SD2149	Si-N-Darl+Di	Sw,Pow,100/100V,15A,100W,B>1000	18j$	Hit	BDV67A..D,BDW83C..D,2SD1026
2SD215(F)	Si-NPN	AF,Sw,40V,1A,0,8W	2a$	Fui	BC140..141,2N1990,2N2102,2N2405..
2SD2150	Si-NPN	=2SD2152:SMD	39b	Rhm	2SC4541,2SD1119,2SD1624,2SD2403
2SD2150-Q	Si-NPN	-	39	Rhm	→2SD2150
2SD2150-R	Si-NPN	-	39	Rhm	→2SD2150
2SD2150-S	Si-NPN	-	39	Rhm	→2SD2150
2SD2151	Si-NPN	AF-Pow,130/80V,10A,30W,20MHz	17c	Mat	2SC3568,2SC3698,2SC4336
2SD2152	Si-NPN	AF-Driver,40V,3A,0,75W,290MHz	7c	Rhm	2SC4487,2SD1507,2SD1617,2SD1864..
2SD2153	Si-NPN	Hi-beta,30/25V,2/3A,B=390..2700	39b	Rhm	2SC3439,2SC3727
2SD2153-E	Si-NPN	-	39	Rhm	→2SD2153
2SD2153-U	Si-NPN	-	39	Rhm	→2SD2153
2SD2153-V	Si-NPN	-	39	Rhm	→2SD2153
2SD2153-W	Si-NPN	-	39	Rhm	→2SD2153
2SD2154	Si-NPN	=2SD2152:0,6W	9c	Rhm	→2SD2152
2SD2155	Si-NPN	AF-Pow,180V,15A,150W,10MHz	77j$	Tos	2SC3281,2SC4029,2SD1975
2SD2156	Si-NPN	Hi-beta,80V,3A,25W,50MHz,B>500	17c	Mat	2SD1944,2SD2076,2SD2092
2SD2156A	Si-NPN	=2SD2156:100V	17c	-	2SD2076,2SD2092
2SD2157	Si-N-Darl+Di	AF-Pow,60V,4A,25W,20MHz,B>1000	17c	Mat	BDT61(A..C)F,2SD1796,2SD1825,2SD1987
2SD2157A	Si-N-Darl+Di	=2SD2157:80V	17c	-	BDT61A..CF,2SD1414,2SD1788,2SD1933..
2SD2158	Si-NPN	Hi-beta,80V,2A,20W,40MHz,B>500	17c	Mat	2SC3852,2SD1776(A),2SD1944,2SD2092,..
2SD2158A	Si-NPN	=2SD2158:100V	17c	-	2SD1776A,2SD2092,2SD2156A
2SD2159	Si-NPN	Hi-beta,Lo-sat,30V,2A,1W,110MHz	7c(9mm)	Rhm	2SC3225,2SC4389,
2SD216(F)	Si-NPN	=2SD215:60V	2a$	Fui	BC140..141,2N1990,2N2102,2N2405..
2SD2161	Si-N-Darl+Di	=2SD1589	17c	Nec	→2SD1589
2SD2162	Si-N-Darl+Di	=2SD1590	17c	Nec	→2SD1590
2SD2163	Si-N-Darl+Di	=2SD1591	17c	Nec	→2SD1591
2SD2164	Si-N	=2SD1593	17c	Nec	→2SD1593
2SD2164	Si-N	=2SD2152:1W	9c	Rhm	→2SD2152
2SD2165	Si-NPN	=2SD1594	17c	Nec	→2SD1594
2SD2166	Si-NPN	=2SD2118:5W	14b	Rhm	2SC3420,2SD1685
2SD2167	Si-NPN	=2SD2169:SMD	39b	Rhm	-
2SD2167-N	Si-NPN	-	39	Rhm	→2SD2167
2SD2167-P	Si-NPN	-	39	Rhm	→2SD2167
2SD2167-Q	Si-NPN	-	39	Rhm	→2SD2167
2SD2168	Si-NPN	=2SD2169	9c	Rhm	-
2SD2169	Si-NPN+Diode	31V,2A,0,5W,100MHz	9c	Rhm	-
2SD217	Si-NPN	AF,Sw-Pow,120/80V,7A,60W,10MHz	23a$	Nec	BD245D,2N3442,2SD551,2SD731..732..
2SD2170	Si-N-Darl+Di	90V,2A,80MHz,B>1000	39b	Rhm	-
2SD2171S	Si-NPN	Hi-beta,Hi-Ueb,30V,1,5A,0,3W,200MHz	41c	Rhm	2SC3070,2SD1582
2SD2172	Si-NPN	=2SD2171S:1W	7c(9mm)	Rhm	2SC4389
2SD2175	Si-NPN	GenP,-/80V,0,7A,0,5W	9c	Rhm	BC639,2SD774,2SC3665,2SD1226,..
2SD2176	Si-N-Darl+Di	Motor-Dr,50V,1,2A,B>1000,Z-Di(B>C)	39b	Sanyo	2SD1626
2SD2177	Si-NPN	AF-Pow,Lo-sat,50V,2A,1W,110MHz	9c	Mat	2SC3328,2SD1207,2SD1835,2SD2182..
2SD2177A	Si-NPN	=2SD2177:60V	9c	-	2SC3328,2SD1207,2SD1835,2SD2182..
2SD2178	Si-NPN	=2SD2177:1,5W	78b	Mat	(BD375,2SD1177..78,2SD1506,2SD1682+)
2SD2179	Si-NPN	GenP,50V,5A,1W,80MHz	9c	Mat	2SD1145,2SD1961..62,2SD2097
2SD218(S)	Si-NPN	=2SD217:150/100V(S=150/120V)	23a$	Nec	BD245D,2N3442,2SD551,2SD731..732..
2SD2180	Si-NPN	GenP,50V,3A,1,5W,80MHz	78b	Mat	(BD785,2SD794(A),2SD1506,2SD1818)
2SD2181	Si-NPN	GenP,Lo-sat,100V,1A,1W,100MHz	9c	Mat	2SC4488,2SD1616A
2SD2182	Si-NPN	GenP,Lo-sat,100V,2A,1W,80MHz	9c	Mat	2SC4489
2SD2183	Si-NPN	=2SD2182:1,5W	78b	Mat	-
2SD2184	Si-NPN	AF,Lo-sat,150/150V,1A,1W,90MHz	9c	Mat	(2SC4614,2SD1665A,2SD1812,2SD1857A)
2SD2185	Si-NPN	-	39	Mat	→2SD2185
2SD2185-R	Si-NPN	-	39	Mat	→2SD2185
2SD2185-S	Si-NPN	-	39	Mat	→2SD2185
2SD2188	Si-NPN	=2SD2085:Iso,30W	17c	Rhm	2SC4553,(2SC4558,2SD1474)
2SD219	Si-NPN	AF,Sw,40V,1A,0,5W,340/5000nS	2a$	Sak	BC140..141,2N1990,2N2102,2N2405..
2SD2191	Si-NPN	=2SD2132:0,4W,Pins=14mm	9c	Rhm	→2SD2132
2SD2192	Si-NPN	=2SD2132:0,4W,Pins=14mm	9c	Rhm	→2SD2132
2SD2193	Si-NPN+Diode	Hi-beta,25V,0,8A,0,9W,B>800	7c(9mm)	Hit	-
2SD2195	Si-N-Darl+Di	GenP,100/100V,2A,B=1k..10k	39b	Rhm	2SD1472

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2SD2196	Si-N-Darl+Di	=2SD1027:Iso,65W	18c	Shi	(2SD1515)
2SD2197M	Si-NPN	=2SC2069:	9c	Rhm	→2SC2069
2SD2198	Si-NPN	Sw,Pow,Lo-sat,60V,5A,30W,100/1600nS	30j$	Sanyo	2SD1904,2SD1906,2SD2200
2SD2199	Si-NPN	Sw,Pow,Lo-sat,60V,7A,40W,200/1200nS	30j$	Sanyo	2SD1905,2SD1907,2SD2201
2SD219F	Si-NPN	=2SD222:	43a$	-	→2SD222
2SD22	Ge-NPN	=2SD19:B=97	2a	Nec	AC127,AC176,AC187,2SD72,2SD352
2SD220	Si-NPN	=2SD219:80V	2a$	Sak	BC140..141,2N1990,2N2102,2N2405..
2SD2200	Si-NPN	Sw,Pow,Lo-sat,90V,5A,30W,100/1600nS	30j$	Sanyo	2SD1906..07,2SD2201
2SD2201	Si-NPN	Sw,Pow,Lo-sat,90V,7A,40W,100/2000nS	30j$	Sanyo	2SD1907
2SD2202	Si-NPN	Sw,Pow,Lo-sat,90V,5A,25W,20MHz	17c	Sanyo	2SC3540,2SC3691,2SC4549,2SC4596
2SD2203	Si-NPN	Sw,Pow,Lo-sat,90V,7A,30W,20MHz	17c	Sanyo	2SC3692,2SC4550,2SD1411
2SD2204	Si-N-Darl+Di	65V,4A,25W,B=2k..15k	17c	Tos	-
2SD2205	Si-N-Darl+Di	=2SD1590	17c	Nec	→2SD1590
2SD2206	Si-N-Darl+Di	GenP,100V,2A,0,9W,100MHz,B>2000	7c(9mm)	Tos	2SD1978,2SD1981
2SD2209	Si-N-Darl+Di	100/100V,4A,15W,B>1000	30j$	Mat	2SC4345,2SD1223,2SD1520
2SD220F	Si-NPN	=2SD223:	43a$	-	→2SD223
2SD221	Si-NPN	=2SD219:110V	2a$	Sak	BC141,2N1990,2N2102,2N2405..
2SD2210	Si-NPN	-	39	Mat	→2SD2210
2SD2210-R	Si-NPN	-	39	Mat	→2SD2210
2SD2210-S	Si-NPN	-	39	Mat	→2SD2210
2SD2210-T	Si-NPN	-	39	Mat	→2SD2210
2SD2211	Si-NPN	=2SD1918:SMD	39b	Rhm	2SC3649,2SD1420..21
2SD2211-N	Si-NPN	-	39	Rhm	→2SD2211
2SD2211-P	Si-NPN	-	39	Rhm	→2SD2211
2SD2211-Q	Si-NPN	-	39	Rhm	→2SD2211
2SD2212	Si-N-Darl+Di	Z-Di(B>C),60V,2/3A,80MHz,B>1000	39b	Rhm	-
2SD2213	Si-N-Darl+Di	AF,150/80V,1,5A,0,9W,B>5000	7c(9mm)	Hit	2SD1579,2SD1659
2SD2214	Si-NPN-Darl	Sw,Pow,60V,8A,25W,20MHz,B>2000	17c	Mat	BD643F,2SD1415..17,2SD1826..
2SD2215(A)	Si-NPN	=2SD1249(A):15W	?30j$	Mat	2SC3075
2SD2216(J)	Si-NPN	GenP,60V,0,1A,150MHz	35a(1,6mm)	Matsushita	2SC4738
2SD2216-Q	Si-NPN	-	35(1,6mm)	Mat	→2SD2216
2SD2216-R	Si-NPN	-	35(1,6mm)	Mat	→2SD2216
2SD2216-S	Si-NPN	-	35(1,6mm)	Mat	→2SD2216
2SD2217	Si-NPN-Darl	Sw,Pow,300/300V,0,3A,25W,45MHz,B>1500	17c	Nec	2SD2109
2SD2218	Si-PNP	Sw,Pow,60V,8A,20W,120MHz,100/530nS	17c	Sanyo	2SC3692..93,2SC3747..48,2SC4550..51
2SD2219	Si-PNP	Sw,Pow,60V,12A,25W,120MHz,200/530nS	17c	Sanyo	2SC3709..10,2SC4065
2SD221F	Si-NPN	=2SD224:	43a$	-	→2SD224
2SD222	Si-NPN	=2SD219:1,5A,10W	43a$	Sak	(BD135,BD226,BD233,BD507,..)
2SD2220	Si-NPN-Darl	AF-Out,100/80V,1A,1,5W,150MHz,B>4000	78b	Mat	(BD139,BD230,2SC2690,2SD1684,..)
2SD2221	Si-NPN-Darl	Pow,160/140V,7A,100W,20MHz,B>5000	18j$	Mat	2SD2255
2SD2222	Si-NPN-Darl	Pow,160/160V,8A,150W,20MHz,B>3500	77j$	Mat	2SD2250,2SD2276
2SD2223	Si-NPN-Darl	Pow,70V,4A,30W,600/4300nS,B>2000	30j$	Sanyo	(BDW23B..C,BDW63B..D,2SD1933,..)
2SD2224	Si-NPN-Darl	Pow,70V,7A,35W,600/4700nS,B>2000	30j$	Sanyo	(BD647,BD899,BDW73B,2SD1415..16..)
2SD2225	Si-NPN	=2SD1211:	9c	Mat	2SC2235,2SC3665,2SD667,2SD1616A
2SD2226K	Si-NPN	=2SD2227S:SMD	35a	Rhm	2SD1938
2SD2226K-U	Si-NPN	-	35	Rhm	→2SD2226K
2SD2226K-V	Si-NPN	-	35	Rhm	→2SD2226K
2SD2226K-W	Si-NPN	-	35	Rhm	→2SD2226K
2SD2227S	Si-NPN	Hi-beta,Hi-Ueb,60V,0,15A,250MHz	41c	Rhm	2SC3069,2SC3071,2SC3836
2SD2228	Si-NPN	GenP,Lo-sat,25V,0,5A,>50MHz	35a(2mm)	NEC	2SD1820,2SD1949
2SD2228-D42	Si-NPN	-	35(2mm)	Nec	→2SD2228
2SD2228-D43	Si-NPN	-	35(2mm)	Nec	→2SD2228
2SD2228-D44	Si-NPN	-	35(2mm)	Nec	→2SD2228
2SD2228-D45	Si-NPN	-	35(2mm)	Nec	→2SD2228
2SD2229	Si-NPN	GenP,Lo-sat,16V,0,5A,0,25W,>50MHz	40c	Nec	2SC3225,2SC3247,2SC4483,2SD1302..
2SD223	Si-NPN	=2SD219:80V,1,5A,10W	43a$	Sak	(BD139,BD230,BD237,BD527,..)
2SD2230	Si-NPN	=2SD2229:SMD	35a	Nec	2SC3265,2SC4519
2SD2231	Si-N-Darl+Di	AF-Pow,120/120V,6A,60W,B>2000	18j$	Sak	2SD1170
2SD2232	Si-NPN-Darl	Sw,Pow,400/300V,8A,30W,20MHz,B>3000	17c	Mat	(2SD1141)
2SD2233	Si-NPN-Darl	Sw,Pow,300/250V,6A,30W,20MHz,B>2700	17c	Mat	2SD1410,2SD2017
2SD2234	Si-NPN	Sw,Pow,1500V,3A,40W,<1/4,5µS	17c	Fjd	BU505F,2SD1575
2SD2236	Si-NPN	Pow,-/100V,5A,60W	16c	Rhm	2SC4385,2SC4689,2SC5099,(BD245D,..)
2SD2237	Si-N-Darl+Di	Pow,-/100V,8A,60W,B>2000	16c	Rhm	BDV65CF,2SD1670,2SD1895
2SD224	Si-NPN	=2SD219:110V,1,5A,10W	43a$	Sak	(BD139,BD230,BD237,BD529,..)

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2SD2240	Si-NPN	-	35(1,6mm)	Mat	→2SD2240
2SD2240(A)	Si-NPN	=2SD814(A):	35a(1,6mm)	Mat	-
2SD2240A	Si-NPN	-	35(1,6mm)	Mat	→2SD2240A
2SD2240A-Q	Si-NPN	-	35(1,6mm)	Mat	→2SD2240A
2SD2240A-R	Si-NPN	-	35(1,6mm)	Mat	→2SD2240A
2SD2240A-S	Si-NPN	-	35(1,6mm)	Mat	→2SD2240A
2SD2240A-T	Si-NPN	-	35(1,6mm)	Mat	→2SD2240A
2SD2240-Q	Si-NPN	-	35(1,6mm)	Mat	→2SD2240
2SD2240-R	Si-NPN	-	35(1,6mm)	Mat	→2SD2240
2SD2240-S	Si-NPN	-	35(1,6mm)	Mat	→2SD2240
2SD2240-T	Si-NPN	-	35(1,6mm)	Mat	→2SD2240
2SD2241	Si-N-Darl+Di	Pow,100V,±4A,25W,B>2000,200/2100nS	17c	Tos	BTD61BF,2SD1414,2SD1589,2SD2079..
2SD2242	Si-N-Darl+Di	AF,Sw-Pow,60V,4A,15W,20MHz,B>1000	78c	Mat	(BDT61(A..C)F,2SD1825,2SD1987,..)
2SD2242A	Si-N-Darl+Di	=2SD2242:80V	78c	-	(BDT61AF..CF,2SD1933,2SD2478,..)
2SD2243	Si-NPN	Lo-sat,60/60V,5A,1W	9b	NEC	2SC4482,2SD1145
2SD2244	Si-NPN	Hi-beta,Lo-sat,60/60V,3A,1W,B>800	9b	NEC	-
2SD2245	Si-N-Darl+Di	60V,±2A,1W,B>2000	9b	NEC	-
2SD2246	Si-N-Darl+Di	80/80V,±2A,1W,B>2000,0,4/1,9µS	9b	NEC	2SD1153,2SD1809,2SD1853,2SD1866
2SD2247	Si-NPN	GenP,55V,0,1A,0,2W,50MHz	7c	Hit	BC167,BC237,BC546..547,2SD767..
2SD2248	Si-N-Darl+Di	80V,±2A,0,9W,100MHz,B>2000	7c(9mm)	Tos	2SD1981
2SD2249	Si-NPN	=2SD965:1W	9c	Mat	2SD1244,2SD1934,2SD1961..62,2SD2097..
2SD2250	Si-NPN-Darl	Sw,Pow,160/140V,7A,90W,20MHz,B>5000	77j$	Mat	2SD2222,2SD2276
2SD2251	Si-NPN+Diode	=2SD2252:Int.Damper-Diode	18c	Sanyo	BU508DF,BU4508AX,2SC3892A,2SC4123,2SC4769..
2SD2252	Si-NPN	CTV-HD,1500/800,7A,60W	18c	Sanyo	BU508AF,BU4508AX,2SC3885A,2SC3895,2SC4770..
2SD2253	Si-NPN+Diode	CRT HD,VGA,1700/600,6A,50W	18c	Tos	2SC4766,BU2720DX
2SD2254	Si-NPN-Darl	Pow,130/110V,6A,70W,20MHz,B>5000	77j$	Mat	2SD2222,2SD2250,2SD2276
2SD2255	Si-NPN-Darl	Pow,160/140V,7A,70W,20MHz,B>5000	18j$	Mat	2SD2221
2SD2256	Si-N-Darl+Di	Sw,Pow,120/120V,25A,120W,B>2000	18j$	Hit	2SD2083
2SD2257	Si-N-Darl+Di	Sw,Pow,100V,±3A,20W,500/2500nS,B>2k	17c	Tos	BDT61BF,2SD1828,2SD2129,2SD1788,..
2SD2258	Si-NPN-Darl	=2SD1198A:1W,Pins=14mm	9c	Mat	→2SD1198A
2SD2259	Si-NPN	=2SD1458:1W,Pins=14mm	9c	Mat	→2SD1458
2SD2260(Z)	Si-NPN	AF,Sw-Pow,40V,3A,25W	22a$	Mat	BD241,BD533,BD933,2N4231..33..
2SD2261	Si-NPN	=2SD662B:0,6W,Pins=14mm	9c	Mat	→2SD662B
2SD2263	Si-NPN-Darl	80/60V,2,5A,B>2000	39b	Sanyo	-
2SD2263	Si-NPN+Diode	25V,0,5A,0,5W	7c	Hit	-
2SD2264	Si-NPN	=2SD2152:	9c	Rhm	→2SD2152
2SD2265	Si-NPN-Darl	Sw,Pow,1000V,1A,35W,20MHz,B>200	30j$	Mat	-
2SD2266	Si-NPN	Sw,Pow,80V,4A,15W,80MHz	78c	Mat	(2SC3540,2SC3691,2SC3746,2SC4549,..)
2SD226A	Si-NPN	=2SD226:60V	22a$	-	BD241A,BD535,BD935,2N4232..33..
2SD226B	Si-NPN	=2SD226:80V	22a$	-	BD241B,BD537,BD937,2N4233..
2SD227	Si-NPN	GenP,30V,0,3A,0,25W,120MHz	7c	Nec,Mic	BC337..338,BC635,BC637,2SC3377..
2SD2271	Si-NPN-Darl	300/200V,±10A,30W,B>500,<1/14µS	17c	Tos	-
2SD2273	Si-NPN-Darl	Pow,100/80V,3A,45W,20MHz,B>5000	77j$	Mat	2SD2254
2SD2274	Si-NPN-Darl	Pow,110/90V,4A,50W,20MHz,B>5000	77j$	Mat	2SD2254
2SD2275	Si-NPN-Darl	Pow,120/100V,5A,60W,20MHz,B>5000	77j$	Mat	2SD2254
2SD2276	Si-NPN-Darl	Pow,160/140V,8A,120W,20MHz,B>5000	77j$	Mat	2SD2222,2SD2250
2SD2279	Si-NPN	=2SD2069:	9c	Rhm	→2SD2069
2SD228	Si-NPN	=2SD227:0,4W	7co	Nec	BC337..338,BC635,BC637,2SC3377..
2SD2280	Si-NPN	Sw,Pow,60V,7A,40W,10MHz,200/1200nS	18c	Sanyo	2SC4385,2SC4688,2SC5099,2SD2064
2SD2281	Si-NPN	Sw,Pow,60V,12A,45W,>30MHz,100/1250nS	18c	Sanyo	2SD2282,2SD2285,(BD545A,2SC3256,..)
2SD2282	Si-NPN	Sw,Pow,60V,15A,50W,20MHz,200/1100nS	18c	Sanyo	(BD545A..D,2SC3256,2SD1065,..)
2SD2283	Si-N-Darl+Di	=2SD2090:1,8W	78c	Rhm	-
2SD2284	Si-N-Darl+Di	Dr,80V,3A,B>2000	?12b	Sanyo	-
2SD2285	Si-NPN	Sw,Pow,60V,20A,40W,300/620nS	18c	Sanyo	-
2SD2287	Si-NPN+Diode	CTV-HD,1500V,3A,50W	23a$	Hitachi	BU706D,2SC3480,2SD1441,2SD1729..
2SD2288	Si-NPN	CTV-HD,1500/800V,3A,50W	23a$	Hitachi	BU706,2SC3484,2SD1495
2SD2289	Si-NPN+Diode	CTV-HD,1500V,5A,50W	23a$	Hitachi	BU706D,2SC3481,2SC3681,2SC4291
2SD229..230	Si-NPN	-		Nec	-
2SD2290	Si-NPN	CTV-HD,1500/800V,5A,50W	23a$	Hitachi	BU706,2SC3485,2SC3685,2SD1496
2SD2291	Si-NPN+Diode	CTV-HD,1500V,6A,50W	23a$	Hitachi	BU2508D,2SC3482,2SC3681,2SC4192
2SD2292	Si-NPN	CTV-HD,1500/800V,6A,50W	23a$	Hitachi	BU2508A,2SC3486,2SC3685,2SD1497
2SD2293	Si-NPN+Diode	=2SD2287:	18j$	Hit	2SD2287,BU4505DX
2SD2294	Si-NPN	=2SD2288:	18j$	Hit	2SD2288,BU4505AX,BU4508AX
2SD2295	Si-NPN+Diode	=2SD2289:	18j$	Hit	→2SD2289

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2SD2296	Si-NPN	=2SD2290:	18j$	Hit	2SD2290,BU4508AX
2SD2297	Si-NPN+Diode	=2SD2291:	18j$	Hit	→2SD2291
2SD2298	Si-NPN	=2SD2292:	18j$	Hit	→2SD2292
2SD2299	Si-NPN+Diode	=2SD2287:Iso	?18c	Hit	BU706DF,BU4505DF,2SD1554,2SD1650,2SD2368
2SD23	Ge-NPN	=2SD19:B=150	2a	Nec	AC127,AC176,AC187,2SD72,2SD352
2SD2300	Si-NPN+Diode	=2SD2289:Iso	?18c	Hit	BU706DF,BU4508DF,2SC4122,2SC4293,2SD1555..
2SD2301	Si-NPN	=2SD2292:Iso	?18c	Hit	BU2508AF,BU4508AF,2SC3486,2SC3685,2SC4143..
2SD2306	Si-N-Darl+Di	Pow,-/60V,4A,B>1000	78c	Rhm	(BD677,BD777,2N6038,2SD1223,2SD1520)
2SD2307	Si-N-Darl+Di	Pow,-/100V,8A,B>1000	78c	Rhm	-
2SD2308	Si-N-Darl+Di	AF,80V,4A,1,2W,40MHz,B=5000	78b	Rhm	(BD679,BD779,2N6039,2SD1223,2SD1520)
2SD2309	Si-NPN-Darl	=2SD1986:	78b	Rhm	(BD677,BD777,2N6038,2SD1223,2SD1520)
2SD231(F)	Si-NPN	AF,Sw-Pow,50/40V,30A,125W,-/11µS	23a$	Fui	BDX41,2N3771,2SD630
2SD2310	Si-NPN+Diode	Sw,Pow,TV-HD,1500/700,1,5A,40W	17c	Mat	BU505DF,2SD2001
2SD2311	Si-NPN	=2SD2290:Iso	?18c	Hit	BU706F,BU4508AF,2SC3894,2SC4142,2SC4830..
2SD2312	Si-NPN	=2SD2227S:0,4W	9c	Rhm	→2SD2227S
2SD2313M	Si-NPN	=2SD2227S:0,4W	9c	Rhm	→2SD2227S
2SD2314	Si-NPN	=2SD2227S:0,4W,Pins=14mm	9c	Rhm	→2SD2227S
2SD2315	Si-NPN	=2SD2227S:0,4W,Pins=14mm	9c	Rhm	→2SD2227S
2SD2318(FS)	Si-NPN	Hi-beta,80/60V,3A,15W,50MHz,B>390	30j$	Rhm	2SD1754
2SD232(F)	Si-NPN	=2SD231:120/100V,-/13,5µS	23a$	Fui	BDW30,2N6032,2N6274..6275
2SD2321	Si-NPN	AF-Pow,40V,5A,0,4W,150MHz	40c	Mat	2SD1244,2SD1934,2SD2249,2SD2097..
2SD2322S	Si-NPN	Lo-sat,40V,0,8A,0,3W,150MHz	41c	Rhm	2SC4485,2SD1616
2SD2323	Si-N-Darl+Di	300/300V,6A,30W,B>500	17c	Hit	-
2SD2324	Si-NPN-Digital+Di	20V,0,8A,150MHz,R2=1kΩ	35a	Sanyo	-
2SD2326	Si-N-Darl+Di	60V,1A,1,2W,150MHz,B>6500	?12b	Mat	-
2SD2327	Si-NPN	AF-Pow,-/160V,12A,120W	77j$	Mat	2SC3280..81,2SD1717..18,2SD2029..
2SD2328	Si-NPN	AF-Pow,180/180V,15A,150W,30MHz	77j$	Mat	2SC3281,2SD1718,2SD1975,2SD2155
2SD2329	Si-NPN	HD,1500/600V,5A,-IBp=2,5A,80W	16c	Mat	BU2508AF,BU706F,BU908F,2SD1884..
2SD232A	Si-NPN	=2SD231:160/140V	23a$	-	BDW32,BDY58,2N6276..6277
2SD233	Si-NPN	-		Nec	-
2SD2330	Si-NPN	HD,1500/600V,7A,100W	16c	Mat	BU508AF,BU2508AF,BU908F,2SD2252,..
2SD2331	Si-NPN+Diode	HD,1500/600V,3A,-IBp=2A,60W	18c	Mat	BU706DF,2SD1554,2SD1650,2SD2089..
2SD2332	Si-NPN	HD,1500/600V,3A,-IBp=2A,60W	18c	Mat	BU706F,2SD1544,2SD1654,2SD1883..
2SD2333	Si-NPN+Diode	HD,1500/600V,5A,-IBp=2,5A,80W	18c	Mat	BU706DF,2SC4293,2SD1555,2SD2125..
2SD2334	Si-NPN	HD,1500/600V,5A,-IBp=2,5A,80W	18c	Mat	BU706F,2SC4142,2SD1655,2SD1884..
2SD233S	Si-NPN+Diode	HD,1500/600V,7A,-IBp=3A,100W	18c	Mat	BU2508DF,2SC4123,2SC4762,2SC4769..
2SD2336	Si-NPN	HD,1500/600V,7A,-IBp=3A,100W	18c	Mat	BU2508AF,2SC4770,2SD1547,2SD2252..
2SD2337	Si-NPN	AF-Pow,200/150V,2A,20W	17c	Hit	2SC3298B,2SC4382,2SD1587
2SD234(G)	Si-NPN	AF,Sw-Pow,60V,3A,25W,3MHz	17j$	Mic,Tos	BD241A,BD535,BD935,2SC3179..
2SD2340	Si-NPN-Darl	AF,Sw-Pow,130/110V,6A,50W,20MHz,B>5k	18j$	Mat	2SD2221,2SD2255
2SD2341	Si-NPN	GenP,200/180V,2A,1,5W,150MHz	78b	Mat	-
2SD2342	Si-NPN	AF,Sw-Pow,150/80V,6A,50W	18j$	Hit	BD245D..F,2SC2837,2SC4467,2SD1046..47
2SD2343	Si-NPN	AF,Sw-Pow,120V,1,5A,5W,80MHz	14b	Rhm	2SC3621,2SD1684,(2SC2690(A),2SD1563)
2SD2344	Si-NPN	AF,Sw-Pow,350/150V,7A,20W	17c	Hit	BU306F,BU406F,2SC4130,2SC4160..
2SD2345	Si-NPN	-	35(1,6mm)	Mat	→2SD2345
2SD2345-R	Si-NPN	-	35(1,6mm)	Mat	→2SD2345
2SD2345-S	Si-NPN	-	35(1,6mm)	Mat	→2SD2345
2SD2345-T	Si-NPN	-	35(1,6mm)	Mat	→2SD2345
2SD2348	Si-NPN+Diode	CTV-HD,1500/600V,±8A,50W	18c	Tos	BU2508DF,BU4522DX,2SC4124,2SC4763,2SD1880..
2SD2349	Si-NPN+Diode	CTV-HD,1500/600V,±10A,50W	18c	Tos	BU2520DF,BU4523DX,2SC4125,2SC4531,2SD1881..
2SD235(G)	Si-NPN	=2SD234:50V	17j$	Mic,Tos	BD241,BD535,BD935,2SC3179..
2SD2350	Si-NPN-Darl	300/300V,6A,40W,B>500	17	Fjd	2SD1071,2SD1113,2SD1307,2SD1976
2SD2351	Si-NPN	=2SD2227S:SMD	35a(2mm)	Rhm	2SC4413
2SD2351-U	Si-NPN	-	35(2mm)	Rhm	→2SD2351
2SD2351-V	Si-NPN	-	35(2mm)	Rhm	→2SD2351
2SD2351-W	Si-NPN	-	35(2mm)	Rhm	→2SD2351
2SD2352	Si-NPN	Hi-beta,60V,2A,25W,17MHz,B>800	17c,	Tos	2SC3852,2SD1776(A),2SD1944,2SD2158(A)
2SD2353	Si-NPN	Hi-beta,60V,3A,25W,18MHz,B>800	17c	Tos	2SC3852,2SD1972,2SD1944,2SD2127,..
2SD235S4	Si-NPN	HD,1500V,7A,-IBp=3A,100W	16c	Mat	BU508AF,BU908F,BU2508AF,2SD2252,..
2SD2355	Si-NPN	HD,1500V,10A,-IBp=4A,100W	16c	Mat	BU2520AF,BU2525AF,2SD1887,2SD2373..
2SD2356	Si-NPN	HD(64kHz),1500V,20A,200W	77j$	Mat	2SC3997,2SC4290A,2SC4897
2SD2357	Si-NPN	Lo-sat,10V,1A,120MHz	39b	Mat	2SC2982,2SC3443,2SD1621
2SD2358	Si-NPN	=2SD2357:	9d	Mat	BC635,2SC4485,2SD1225,2SD1616..
2SD2359	Si-NPN	Lo-sat,20V,1A,100MHz	39b	Mat	2SC2982,2SC3443,2SD1621

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2SD236	Si-NPN	AF,Sw-Pow,40V,1,5A,10W	22a$	Sak	BD239,BD241,BD933,2N4231..33..
2SD2360	Si-NPN	GenP,-/20V,0,5A	9	Mat	BC337,2SC4485,2SD1226,2SD2322S..
2SD2361	Si-NPN	GenP,60V,1A,1,2W,150MHz	?12b	Mat	(BD517,BD525,2SC2194,2SD1801,..)
2SD2362	Si-NPN	GenP,50V,2A,1,2W,130MHz	?12b	Mat	(BD509,BD515,2SC3076,2SD1801,..)
2SD2363	Si-NPN	GenP,60V,3A,1,2W,25MHz	?12b	Mat	(2SC3386,2SD1221,2SD1802,2SD1805,..)
2SD2364	Si-NPN	GenP,80V,1A,1,2W,140MHz	?12b	Mat	(BD519,BD527,BD529,2SC4135,..)
2SD2365	Si-NPN	GenP,150V,1A,1,2W,90MHz	?12b	Mat	(2SC2384,2SC2983,2SD1220,2SD1918,..)
2SD2366	Si-NPN	Sw,400/400V,0,5A,1,2W,30MHz	?12b	Mat	(2SC2752,2SC3362,2SC46152SD1053)
2SD2367	Si-NPN+Diode	HD,1500V,3A,-IBp=2,5A,50W	18c	Mat	BU70SDF,BU4504DX,2SD1554,2SD1877,2SD2089..
2SD2368	Si-NPN+Diode	HD,1500/700V,3,5A,60W	18c	Mat	BU706DF,BU4506AX,2SD1554,2SD1877,2SD2089..
2SD2369	Si-NPN+Diode	HD,1500V,4A,-IBp=2,5A,70W	18c	Mat	BU706DF,BU4506DX,2SD1555,2SD209S,2SD2125..
2SD237	Si-NPN	=2SD236:80V	22a$	Sak	BD239B,BD241B,BD937,2N4233..
2SD2370	Si-NPN+Diode	HD,1500/700V,5A,100W	18c	Mat	BU706DF,BU4507AX,2SD1555,2SD209S,2SD2125..
2SD2371	Si-NPN+Diode	HD,1500V,7A,100W	18c	Mat	BU2508DF,BU4508DX,2SC3893A,2SC4124,2SD1880,..
2SD2372	Si-NPN	HD,1500/600V,7A,-IBp=3A,100W	18c	Mat	BU2508AF,BU4507AX,2SC3895,2SC4757,2SD2252..
2SD2373	Si-NPN	HD,1500/600V,10A,-IBp=4A,100W	18c	Mat	BU4508AX,BUH715,2SC3897,2SC4542,2SD1887..
2SD2374	Si-NPN	Sw,Pow,60V,3A,25W,30MHz,500/2900nS	17c	Mat	2SD1762,2SD1913,2SC3690
2SD2374A	Si-NPN	=2SD2374:80V	17c	-	2SC3690
2SD2375	Si-NPN	Hi-beta,80V,3A,25W,50MHz,B>500	17c	Mat	2SD1273,2SD1944,2SD2092,2SD2156
2SD238	Si-NPN	=2SD236:110V	22a$	Sak	BD239C,BD241C,BD939,2SD381..382,..
2SD2381	Si-NPN	CTV-HD,1500/800V,3A,40W	?18c	Hit	BU706F,BU4505AF,2SD1544,2SD1654,2SD1883
2SD2383	Si-NPN	Sw,400/300V,20mA,90MHz	35a	NEC	-
2SD2384	Si-NPN-Darl	AF,Sw-Pow,140/140V,7A,100W,B>5000	77j$	Tos	2SD2222,2SD2250,2SD2276
2SD2385	Si-NPN-Darl	AF,Sw-Pow,140/140V,8A,120W,B>5000	77j$	Tos	2SD2222,2SD2250,2SD2276
2SD2386	Si-NPN-Darl	=2SD2384:70W	18j$	Tos	2SD2221,2SD2255
2SD2387	Si-NPN-Darl	=2SD2385:80W	18j$	Tos	BDV67C..D,2SD1210
2SD2388	Si-N-Darl+Di	=2SD2090:1,2W	78b	Rhm	-
2SD2389	Si-NPN-Darl	AF-Pow,160/150V,8A,80W,80MHz,B>5000	18j$	Sak	BDV67D,2SD1123
2SD239..240	Si-NPN	-		Sak	-
2SD2390	Si-NPN-Darl	AF-Pow,160/150V,10A,100W,55MHz,B>5000	18j$	Sak	BDV67D,2SD1123,2SD1027,2SD1515
2SD2391	Si-NPN	AF,Lo-sat,60V,2A,210MHz	39b	Rhm	2SC4409
2SD2391-P	Si-NPN	-	39	Rhm	→2SD2391
2SD2391-Q	Si-NPN	-	39	Rhm	→2SD2391
2SD2394	Si-NPN	AF-Pow,80V,3A,25W,8MHz	17c	Rhm	BD937F,BDT31..F,2SC3475,2SC3851,..
2SD2395	Si-NPN	AF-Pow,60V,3A,25W,100MHz	17c	Rhm	BD935F,BDT31..F,2SD1585,2SD1985,..
2SD2396	Si-NPN	=2SD1943:Iso,30W	17c	Rhm	2SD1273,2SD2092,2SD2156,2SD2375,..
2SD2397	Si-N-Darl+Di	=2SD1764	17c	Rhm	→2SD1764
2SD2398	Si-N-Darl+Di	AF-Pow,100V,2A,20W,B=1k..10k	17c	Rhm	2SD1828,2SD1890,2SD2129,2SD2257,..
2SD2399	Si-N-Darl+Di	AF-Pow,80V,4A,30W,40MHz,B=1k..10k	17c	Rhm	BDT61..F,2SD1414,2SD1788,2SD1933,..
2SD24	Si-NPN	Vid-Pow,300V,0,1A,6W(Tc=70°),25MHz	22a$	Sanyo	2SC1505..1507,2SC1755..1757,2SC1905,..
2SD2400	Si-NPN	AF-Pow,120V,1,5A,20W,80MHz	17c	Rhm	2SC3364,2SC3564,2SC4883(A),2SD1763,..
2SD2400A	Si-NPN	=2SD2400:160V	17c	Rhm	2SC3364,2SC4159,2SC4370,2SC4883A..
2SD2401	Si-NPN-Darl	AF-Pow,160/150V,12A,150W,55MHz,B>5000	20j$	Sak	-
2SD2402	Si-NPN	Lo-sat,50V,5A,170MHz,275/530nS	39b	Nec	2SD1628
2SD2402-EX	Si-NPN	-	39	Nec	→2SD2402
2SD2402-EY	Si-NPN	-	39	Nec	→2SD2402
2SD2402-EZ	Si-NPN	-	39	Nec	→2SD2402
2SD2403	Si-NPN	Lo-sat,80V,3A,130MHz,150/665nS	39b	Nec	2SC4541
2SD2403-GX	Si-NPN	-	39	Nec	→2SD2403
2SD2403-GY	Si-NPN	-	39	Nec	→2SD2403
2SD2403-GZ	Si-NPN	-	39	Nec	→2SD2403
2SD2406	Si-NPN	GenP,Pow,80V,4A,25W,8MHz	17c	Tos	2SC3851,2SC3691,2SD1408,2SD2000..
2SD2407	Si-NPN	Sw,Pow,60V,3A,10W,220MHz,500/2900nS	30j$	Mat	2SC4522,2SD1221,2SD1760,2SD1802,..
2SD2408	Si-NPN	Sw,Pow,50V,2A,10W,150MHz	30j$	Mat	2SC3076,2SD1078..1079,2SD1801..
2SD2409	Si-NPN	Sw,Pow,50V,5A,10W,80MHz	30j$	Mat	2SC3072,2SC3518,2SC3592,2SD1805,..
2SD241	Si-NPN	AF,Sw-Pow,60V,4A,25W	22a$	Sak	BD243A,BD535,BDW25,BDX25..
2SD2410	Si-N-Darl+Di	Sw,Pow,100V,2A,10W,20MHz,B=1k..10k	30j$	Mat	2SD1980
2SD2411	Si-N-Darl+Di	Sw,Pow,200V,2A,10W,B=1k..10k	30j$	Mat	-
2SD2411K	Tr		-	Rohm	-
2SD2412	Si-NPN	Sw,Pow,400/300V,0,75A,10W,180MHz	30j$	Mat	2SC3362,2SC3632,2SC4615,2SD1053
2SD2413	Si-NPN	Sw,400/400V,0,1A,40MHz	39b	Mat	2SC4548
2SD2414(SM)	Si-NPN	Sw,Pow,Lo-sat,100V,7A,40W,10MHz	30j$	Tos	2SD1257(A)
2SD2415	Si-NPN+Diode	25V,0,5A,0,5W	7c	Hit	-
2SD2416	Si-NPN-Darl	60V,1A,150MHz,B=6,5k..40k	39b	Mat	2SD1470,2SD1511,2SD1834

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2SD242	Si-NPN	=2SD241:90V	22a$	Sak	BD243C,BD539B,BDW25,BDX25..
2SD2420	Si-NPN-Darl	Pow,60V,4A,40W,20MHz,B>2000	17c	Mat	BDT61BF..CF,2SD1589,2SD1928,2SD2079+
2SD2421	Si-N-Darl+Di	=2SD2422:1,8W	78c	Rhm	-
2SD2422	Si-N-Darl+Di	Pow,100/100V,7A,30W,40MHz,B>1000	17c	Rhm	2SD1791,(BD647F,2SD1415)
2SD2423	Si-N-Darl+Di	50V,1,5A,B>2000	39b	Hit	-
2SD2425	Si-NPN	Sw,60V,5A,600/880nS	39b	Nec	2SD2098,2SD2402
2SD2425-AB1	Si-NPN	-	39	Nec	→2SD2425
2SD2425-AB2	Si-NPN	-	39	Nec	→2SD2425
2SD2425-AB3	Si-NPN	-	39	Nec	→2SD2425
2SD2426	Si-NPN-Darl	GenP,100/80V,2A,1,5W,80MHz	?12b	Sanyo	-
2SD2428	Si-NPN+Diode	CTV-HD,Double Scan,1700/600V,8A,200W	77j$	Tos	(S3934..35,2SC4532,2SC4608)
2SD243	Si-NPN	=2SD241:110V	22a$	Sak	BD243C,BD539C,BDW25,BDX25..
2SD2432	Si-NPN	=2SD602:	35d	Mat	→2SD602
2SD2432-Q	Si-NPN	-	?35	Mat	→2SD2432
2SD2432-R	Si-NPN	-	?35	Mat	→2SD2432
2SD2432-S	Si-NPN	-	?35	Mat	→2SD2432
2SD2433	Si-NPN	=2SD1030:	35d	Mat	→2SD1030
2SD2433-R	Si-NPN	-	?35	Mat	→2SD2433
2SD2433-S	Si-NPN	-	?35	Mat	→2SD2433
2SD2433-T	Si-NPN	-	?35	Mat	→2SD2433
2SD2434	Si-NPN-Darl	=2SD1478:	35d	Mat	→2SD1478
2SD2434-P	Si-N-Darl+Di	-	?35	Mat	→2SD2434
2SD2434-Q	Si-N-Darl+Di	-	?35	Mat	→2SD2434
2SD2434-R	Si-N-Darl+Di	-	?35	Mat	→2SD2434
2SD2436	Si-NPN	=2SD1328:	35d	Mat	→2SD1328
2SD2436-R	Si-NPN	-	?35	Mat	→2SD2436
2SD2436-S	Si-NPN	-	?35	Mat	→2SD2436
2SD2436-T	Si-NPN	-	?35	Mat	→2SD2436
2SD2437	Si-N-Darl+Di	AF-Pow,120/120V,6A,60W,80MHz,B>2000	18c	Sak	2SD1893..95,2SD2045
2SD2438	Si-N-Darl+Di	AF-Pow,160/150V,8A,70W,80MHz,B>5000	18c	Sak	2SD1894..95,(2SD2221,2SD2255)
2SD2439	Si-N-Darl+Di	AF-Pow,160/150V,10A,70W,55MHz,B>5000	18c	Sak	2SD1895,(2SD2390)
2SD244	Si-NPN	=2SD241:130V	22a$	Sak	BD243D,BDW25,BDX25,2SD960..961..
2SD2440	Si-NPN	Hi-beta,Hi-Ueb,100V,6A,40W,5MHz	16c	Tos	-
2SD2441	Si-NPN	Lo-sat,10V,1,5A,190MHz	39b	Mat	2SC2982,2SC3443,2SD1621
2SD2443	Si-NPN	Pow,20V,0,7A,10W,B>1000,150MHz	30j$	Mat	-
2SD2444K	Si-NPN	Lo-sat,15V,1A,200MHz	35a	Rohm	-
2SD2449	Si-NPN-Darl	Pow,160/160V,10A,150W,30MHz,B>3000	77j$	Tos	-
2SD245	Si-NPN	-		Sak	-
2SD2450	Si-NPN	AF-Dr/Out,-/32V,2A,0,9W	7c(9mm)	Rhm	2SC4145,2SD1207,2SD2069
2SD2451	Si-NPN	AF-Dr/Out,-/160V,1,5A,0,9W	7c(9mm)	Rhm	2SC4614,2SD1665A,2SD1812,2SD1857A
2SD2452	Si-N-Darl+Di	31V,2A,1,2W,B>1000	78b	Rhm	-
2SD2453	Si-NPN	AF,Sw-Pow,80V,3A,10W,100MHz,B>500	30j$	Mat	2SD2318
2SD2454	Si-NPN+Diode	CTV-HD,1700/600V,7A,50W	18c	Tos	BU27200X,BUH517D,2SC4963
2SD2455	Si-PNP	GenP,40/25V,1A	40	Mat	BC637,BC639,2SD667,2SD1616(A)..
2SD2456	Si-NPN	GenP,-/40V,1,5A	40	Mat	2SD1051,2SD1207,2SD1665,2SD1857..
2SD2457	Si-NPN	50V,1,5A,150MHz	39b	Mat	→2SD2457
2SD2457-Q	Si-NPN	-	39	Mat	→2SD2457
2SD2457-R	Si-NPN	50V,1,5A,150MHz	39	Mat	→2SD2457
2SD2457-S	Si-NPN	-	39	Mat	→2SD2457
2SD2458	Si-NPN	GenP,-/100V,1A	39b	Mat	2SC3646..47,2SD1418..19
2SD2459	Si-NPN	Lo-sat,150/150V,1A,90MHz	39b	Mat	2SC3649,2SD1420..21
2SD246	Si-NPN	TV-HD,1500V,4,5A,16W(Tc=90°)	23a$	Matsushita	BU208..209(A),BU706,2SC2928..
2SD2460	Si-NPN	Hi-beta,Hi-Ueb,20V,0,7A,0,3W,55MHz,B=1k..2,5k	40c	Mat	2SC3616,2SC4204
2SD2461	Si-NPN	Hi-beta,60V,2A,1,3W,B>800	12b	Tos	(2SC3808)
2SD2462	Si-NPN	Hi-beta,60/60V,3A,1,3W,B>800	12b	Tos	(2SD1694)
2SD2463	Si-N-Darl+Di	31V,±2A,1W,B>2000	9b	NEC	-
2SD2464	Si-NPN	Lo-sat,15V,5A,0,75W,170MHz,B>300	7c	Mat	2SC4482,2SD1145
2SD2465	Si-NPN	Pow,Lo-sat,40V,4A,25W,120MHz	17c	Mat	2SC3299,2SC3746,2SC4881
2SD2465A	Si-NPN	=2SD2465:50V	17c	-	2SC3299,2SC3746,2SC4881
2SD2466	Si-NPN	Pow,Lo-sat,40V,10A,40W,120MHz	17c	Mat	2SC3709,2SC4064..65,2SD1445(A)
2SD2466A	Si-NPN	=2SD2466:50V	17c	-	2SC3709,2SC4064..65,2SD1445A
2SD2467	Si-NPN	=2SD1254:	17c	Mat	→2SD1268
2SD2468	Si-NPN	=2SD1255:	17c	Mat	→2SD1269
2SD2469(A)	Si-NPN	=2SD1257(A):	17c	Mat	→2SD1271(A)

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2SD247	Si-NPN	AF,Sw-Pow,80V,5A,50W	23a$	old	BD245B,BDV93,BDX93,2N5632..33..
2SD2470	Si-NPN	Strobo,15V,5A,0,4W,170MHz	41c	Rhm	2SD1244,2SD1934,2SD2249,2SD2497..
2SD2472	Si-NPN	Lo-sat,10V,0,5A,120MHz	35d	Mat	2SC4577
2SD2473	Si-NPN	Lo-sat,20V,0,5A	35d	Mat	2SC4519,2SC4577
2SD2474	Si-NPN	Lo-sat,10V,2A,180MHz	39b	Mat	2SC3443,2SC2982,2SD1621
2SD2478	Si-NPN-Darl	Pow,80/80V,4A,30W,40MHz,B>1000	17c	Rhm	2SD1788,(BDT61BF,2SD1414,2SD1589..)
2SD2479	Si-N-Darl+Di	Pow,120V,2A,1,5W,150MHz,B>4000	78b	Mat	-
2SD248	Si-NPN	-		Tos	-
2SD2480	Si-N-Darl+Di	100V,2A,1,3W,100MHz,B>2000	12b	Tos	(2SD1980,2SD2410)
2SD2481	Si-N-Darl+Di	30V,1,5A,1,3W,B>4000,180/900nS	12b	Tos	(2SD947)
2SD2482	Si-NPN	-	35(2mm)	Mat	→2SD2482
2SD2483	Si-NPN	-	35(2mm)	Mat	→2SD2483
2SD2484	Si-NPN	Lo-sat,50V,2A,0,9W	7c(9mm)	Hit	2SC3726,2SD1207,2SD2069,2SD2177,..
2SD2485	Si-NPN	=2SD2484:80V	7c(9mm)	Hit	2SC3328,2SC4489,2SD2182
2SD2486	Si-NPN	Hi-beta,Lo-sat,60V,5A,70MHz,B>500	17c	Mat	2SD1948,2SD2075..2076
2SD2488	Si-NPN-Darl	Pow,200/200V,12A,130W,70MHz,B>5000	18j$	Sak	-
2SD2489	Si-NPN-Darl	=2SD2488:17A,200W	20j$	Sak	-
2SD249	Si-NPN	AF,Sw-Pow,50V,30A,125W,0,8MHz	23a$	Fui	BDX41,2N3771,2SD630
2SD2490	Si-NPN-Darl	=2SD2488:Iso,85W	18c	Sak	-
2SD2491	Si-NPN	Vid-Out,160/160V,0,1A,8W,140MHz	14b	Hit	2SC3788,2SC3955..56
2SD2492	Si-NPN	=2SD2491:200/200V	14b	Hit	2SC3788,2SC3955..56
2SD2493	Si-NPN-Darl	AF-Pow,110/110V,6A,60W,60MHz,B>5000	18j$	Sak	2SD2340,2SD2386
2SD2494	Si-NPN-Darl	=2SD2493:Iso	18c	Sak	2SD1893..94,2SD2438
2SD2495	Si-NPN-Darl	=2SD2493:Iso,30W	17c	Sak	2SD2025
2SD2496	Si-NPN	=2SD601A:	35d	Mat	→2SD601A
2SD2496-Q	Si-NPN	-	ч35	Hit	→2SD2496
2SD2496-R	Si-NPN	-	ч35	Hit	→2SD2496
2SD2496-S	Si-NPN	-	ч35	Hit	→2SD2496
2SD2497	Si-NPN	Lo-sat,40/20V,5A,0,75W	7c	Hit	2SC4482,2SD1145,(2SD1244,2SD2249..)
2SD2498	Si-NPN	CTV-HD,1500/600V,6A,50W	18c	Tos	BU2508AF,BU4508AX,2SC3884A,2SC3894,2SC4830,..
2SD2499	Si-NPN+Diode	CTV-HD,1500/600V,6A,50W	18c	Tos	2SC4764,BU4508DX
2SD24Y	Si-NPN	=2SD24:0,15A,8MHz	22a$	-	2SC1505..1507,2SC1755..1757,2SC1905,..
2SD25	Ge-NPN	AF,25V,0,1A,0,11W	2a	Nec	AC127,AC176,AC187,2SD30
2SD250	Si-NPN	=2SD249:100V,0,6MHz	23a$	Fui	BDY29,MJ802,2SD797
2SD2500	Si-NPN	TV-HD,1500/600V,10A,50W	18c	Tos	BU2520AF,BUH715,2SC4542,2SC4759..
2SD2504	Si-NPN	Lo-sat,15V,5A,0,75W,170MHz,B>300	7c	Mat	2SC4482,2SD1145
2SD251	Si-NPN	AF,Sw-Pow,200/200V,2A,30W,-/7,5μS	22a$	Fui	BD239F,BUX67,2SD610,2SD1138..
2SD2510	Si-NPN+Diode	HD,1500V,3A,-IBp=2A,60W	18c	Mat	BU706DF,2SD1291,2SD1876,2SD2367..
2SD2511	Si-NPN	HD,1500V,3A,-IBp=2A,60W	18c	Mat	BU706F,BU4506AX,2SD1544,2SD1654,2SD1883..
2SD2512	Si-NPN+Diode	HD,1500V,5A,-IBp=2,5A,80W	18c	Mat	BU706DF,BU4508DX,2SD1555,2SD1730,2SD2095..
2SD2513	Si-NPN	HD,1500V,5A,-IBp=2,5A,80W	18c	Mat	BU706F,BU4508AX,2SC4830,2SD1545,2SD1655..
2SD2514	Si-NPN+Diode	HD,1500V,7A,-IBp=3A,100W	18c	Mat	BU2508DF,BU4523DX,2SC4762,2SC4916,2SD2251..
2SD2515	Si-NPN	HD,1500V,7A,-IBp=3A,100W	18c	Mat	BU2508AF,BU4523AX,2SC3895,2SC4757,2SD2252..
2SD2521	Si-NPN+Diode	HD,1700V,2,5A,-IBp=1,5A,60W	18c	Mat	-
2SD2522	Si-NPN+Diode	HD,1700V,4A,-IBp=2,5A,80W	18c	Mat	2SC4765
2SD2523	Si-NPN+Diode	HD,1700V,6A,-IBp=3A,90W	18c	Mat	2SC4766,2SC4962,2SD2253,BU2720DX
2SD2524	Si-NPN+Diode	HD,1700V,8A,-IBp=4,5A,100W	18c	Mat	BU2708DF,BUH517D,2SC4963
2SD2525	Si-NPN	AF,60V,3A,1,8W,3MHz	15c	Tos	2SD1683,(BD785,2SD1506,2SB1818)
2SD2526	Si-N-Darl+Di	100V,5A,1,8W,B=2k..15k	15c	Tos	-
2SD2527	Si-NPN	Hi-beta,80V,4A,40W,30MHz,B>500	17c	Mat	2SC4553,2SC4558,2SD2076,2SD2188..
2SD2528	Si-NPN	Hi-beta,Lo-sat,80V,5A,40W,30MHz,B>500,400/2600nS	17c	Mat	2SC4553,2SC4558,2SD2076,2SD1474
2SD2529	Si-NPN	=2SD1938:	35d	Mat	→2SD1938
2SD2529-S	Si-NPN	-	?3S	Mat	→2SD2529
2SD2529-T	Si-NPN	-	?3S	Mat	→2SD2529
2SD2530	Si-NPN-Darl	100/100V,5A,15W,20MHz,B=1k..10k	78	Mat	(BD647F,2SD1785,2SD1829,2SD1928,..)
2SD2531	Si-NPN	AF-Pow,60V,4A,25W,3MHz	17c	Tos	BD949F,2SC3299,2SC3746,2SD1667..
2SD2532	Si-NPN	-	39	Hit	→2SD2532
2SD2533	Si-NPN	-	39	Hit	→2SD2533
2SD2536	Si-N-Darl+Di	85V,2A,0,9W,B>2000,Rb=3,6kΩ,Rbe=5kΩ	7c(9mm)	Tos	-
2SD2537	Si-NPN	Hi-beta,30V,1,2A,B=820..2700	39b	Rhm	2SC3727,2SD1870,2SD1950
2SD2537-V	Si-NPN	-	39	Rhm	→2SD2537
2SD2537-W	Si-NPN	-	39	Rhm	→2SD2537
2SD2538	Si-NPN-Darl	Sw,Pow,60V,2A,35W,20MHz,B>2000	17c	Mat	2SD1828,2SD1890,2SD2129,2SD2257..
2SD2539	Si-NPN+Diode	CTV-HD,1500/600V,7A,50W	18c	Tos	BU2508DF,BU4522DX,2SC3892A,2SC4123,2SD2251,..

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2SD254	Si-NPN	AF-Pow,70V,2A,20W	22a$	Nec	BD241A,BD937,BDY78,2SC1398..
2SD2540	Si-NPN	-	39	Hit	→2SC2540
2SD2544	Si-NPN	=2SD2486:15W	78c	Mat	(→2SD2486)
2SD2549	Si-NPN	AF,Sw-Pow,80V,3A,20W,30MHz	17c	Mat	BDT31AF..CF,2SC3690..91,2SD2061..
2SD255	Si-NPN	AF-Pow,70V,2A,20W	22a$	Nec	BD241A,BD937,BDY78,2SC1398..
2SD2550	Si-NPN	HD,1700/600V,4A,50W	18c	Tos	BUH417,2SC4761,2SC4796,2SC4806
2SD2551	Si-NPN	HD,1700/600V,5A,50W	18c	Tos	BU2720DX,BUH417,2SC4761,2SC4796,2SC4806
2SD2553	Si-NPN+Diode	CTV-HO,1700/600V,8A,50W	18c	Tos	BU2708DF,BU2725DX,BUH517D,2SC4963
2SD2554	Si-NPN-Darl	Pow,160/160V,7A,120W,20MHz,B>3500	77j$	Mat	2SD2222,2SD2250,2SD2276,2SD2449
2SD2556	Si-NPN	Lo-sat,-/80V,5A	30j$	Mat	2SC5103
2SD2557	Si-NPN-Darl	Sw,Pow,Sw-Reg,200/200V,5A,70W,B>1500	18j$	Sak	-
2SD2558	Si-NPN-Darl	=2SD2557:Iso,60W	18c	-	-
2SD2559	Si-NPN	HD,1500/600V,8A,50W	18c	Tos	BU2515AF,2SC3886A,2SC4758
2SD256	Si-NPN	AF,Sw-Pow,60/40V,4A,25W,1270/3300nS	22a$	Sak	BD243A,BD535,BDY79,2SC3179..
2SD2560	Si-NPN-Darl	Sw,Pow,Sw-Reg,150/150V,15A,130W,B>5000	18j$	Sak	(BDV67D)
2SD2561	Si-NPN-Darl	=2SD2560:17A,200W	20j$	Sak	-
2SD2562	Si-NPN-Darl	=2SD2560:Iso,85W	18c	Sak	(BDV67DF)
2SD2565	Si-NPN	Sw,400/400V,0,5A,1W,30MHz	9c	Mat	2SC4645,2SD1350
2SD2568	Si-NPN	Sw,Pow,400/400V,0,5A,10W,13,5MHz	30j$	Rhm	2SC3075,2SC3129,2SC3588,2SC4499
2SD257	Si-NPN	=2SD256:90/60V	22a$	Sak	BD243B,2SD712,BDY79,2SC3258..
2SD2571	Si-NPN-Darl	Pow,100/100V,2A,25W,B=2000..15000	17c	Tos	2SD1828,2SD1890,2SD2129,2SD2257..
2SD2573	Si-NPN	Hi-beta,80V,3A,50MHz,B=500..2500	78b	Mat	(2SC3852,2SD1273,2SD2318,2SD2375)
2SD2575	Si-NPN	Hi-beta,Lo-sat,15V,5A,0,75W,170MHz	7	Mat	-
2SD2576	Si-NPN	AF-Pow,80V,3A,25W,8MHz	17c	Rhm	BD937F,BDT31..F,2SC3475,2SC3851,..
2SD2578	Si-NPN+Diode	CTV-HD,1500/800V,8A,60W	18c	Sanyo	BU2508DF,2SC4124,2SC4763,2SC5149
2SD2579	Si-NPN	CTV-HD,1500/800V,8A,60W	18c	Sanyo	BU2508AF,2SC3886A,2SC3896,2SC4758
2SD258	Si-NPN	=2SD256:110/80V	22a$	Sak	BD243C,BD539D,BD955,BDY79..
2SD2580	Si-NPN+Diode	CTV-HD,1500/800V,10A,70W	18c	Sanyo	BU2520DF,BU2522DF,2SC4125,2SC4878
2SD2581	Si-NPN	CTV-HD,1500/800V,10A,70W	18c	Sanyo	BU2520AF,BU2522AF,BUH715,2SC5129
2SD2584	Si-NPN-Darl	Sw,Pow,120/100V,7A,20W,B>2000	30j$	Tos	-
2SD2586	Si-NPN	HD,1500/600V,5A,50W	18c	Tos	BU2508AF,2SC3884A,2SC3894,2SC4830
2SD2589	Si-NPN-Darl	AF,Sw-Pow,110V,6A,50W,60MHz,B>5000	17j$	Sak	-
2SD259	Si-NPN	=2SD256:130/100V	22a$	Sak	BD243D,BD941,2SC2516,2SD960..961,..
2SD2593	Si-NPN	AF,Sw-Pow,-/60V	17c	Mat	BD937F,BDT31AF..CF,2SC3690..
2SD2594	Si-NPN	Hi-beta,-/60V,3A	17c	Mat	2SD1944,2SD2092,2SD2156,2SD2396..
2SD2595	Si-NPN-Darl	Sw,Pow,-/60V,2A	17c	Mat	2SD1828,2SD1890,2SD2129,2SD2257..
2SD2598	Si-NPN-Darl	AF,60V,0,5A,1W,200MHz,B>4000	9c	Mat	2SD1198,2SD2116,2SD2258
2SD2599	Si-NPN	HD,1500/600V,3,5A,40W	18c	Tos	BU706F,2SD1544,2SD1654,2SD1883..
2SD26	Si-NPN	AF,Sw-Pow,40V,7A,50W	23a$	Mit	BD245,BDV91,BDX91,2N5873..5874..
2SD260	Si-NPN	AF,Sw-Pow,100V,5A,50W	23a$	old	BD245C,BDV95,BDX95,2N5632..33..
2SD2600	Si-NPN-Darl	Pow,110/100V,8A,35W,>20MHz,B>1500	-	Sanyo	-
2SD2604	Si-NPN-Darl	Sw,Pow,110/95V,5A,20W,B>2000	17c	Tos	BD649F,2SD1315,2SD1336,2SD1785..
2SD2607	Si-N-Darl+Di	Pow,100V,8A,30W,B=1k..20k,40MHz	17c	Rhm	2SD1791,2SD1793,2SD1830,2SD2422..
2SD261	Si-NPN	GenP,40V,0,5A,0,5W,160MHz	7co	Nec,Mic	BC337,BC535,BC637,2SC3377..
2SD2611	Si-NPN	AF,Sw-Pow,100V,7A,30W,5MHz	17c	Rhm	BDX78F,2SC3692,2SC4550,2SD1411
2SD2614	Si-N-Darl+Di	Pow,60±10V,5A,25W,B=2k..30k	17c	Rhm	2SD1417,2SD1595,2SD1826,2SD2131,+
2SD2615	Si-N-Darl+Di	AF-Pow,120V,6A,30W,40MHz,B>2000	17c	Rhm	BD649F,2SD1773,2SD1785
2SD2616	Si-NPN	AF,Sw-Pow,100V,5A,30W,8MHz	17c	Rhm	BD953F,2SC3691,2SC4549,2SD1411
2SD2618	Si-N-Darl+Di	AF-Pow,80V,4A,30W,40MHz,B>1000	17c	Rhm	BDT61AF,2SD1933,2SD2399,2SD2478..
2SD262	Si-NPN	Sw,Pow,300/140V,12A,125W	23a$	Sony	BUW74..75,BUX42,MJ15022,2SC3043..
2SD2629	Si-NPN+Diode	CTV-HD,1500/800V,6A,35W	17c	Sanyo	BU506DF,BU1508DX
2SD263..264	Si-NPN	-		Org	-
2SD2634	Si-NPN+Diode	CTV-HD,1500/800V,8A,65W	18c	Sanyo	BU2515DF,2SC4124,2SC5043,2SD1880
2SD265	Si-NPN	Sw,Pow,800/400V,6A,100W,B>15	23a$	Org	BU326(A),BU426(A),BU526,BUX47..
2SD266	Si-NPN	=2SD265:B>30	23a$	Org	BU326(A),BU426(A),BU526,BUX47..
2SD267..270	Si-NPN	-		Org	-
2SD26A	Si-NPN	=2SD26:60V	23a$	-	BD245A,BDV91,BDX91,2N5873..5874,..
2SD26B	Si-NPN	=2SD26:100V	23a$	-	BD245C,BDV95,BDX95,2N5632..5633,..
2SD26C	Si-NPN	=2SD26:150V	23a$	-	BD245D,BDX11,2N3442,2SD731..732..
2SD27	Ge-NPN	AF-Dr/Out,32V,0,5A,0,28W	2a	Mat	AC127,AC176,AC187,2SD72,2SD352
2SD271	Si-NPN	Sw,Pow,800/400V,2A,30W,B>15	22a$	Org	BUV36(A),BUX84..85,2SC3531
2SD272	Si-NPN	=2SD271:B>30	22a$	Org	BUV36(A),BUX84..85,2SC3531
2SD273	Si-NPN	Sw,Pow,800/400V,5A,80W,B>15	23a$	Org	BUS11(A),BUW11(A),2SC3796(A)..
2SD274	Si-NPN	=2SD273:B>30	23a$	Org	BUS11(A),BUW11(A),2SC3796(A)..

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2SD275..279	Si-NPN	-		Org	-
2SD28	Si-NPN	AF,Sw-Pow,70/40V,3A,18W	22a$	aon	BD241A,BD537,BD937,2SD712..
2SD280	Si-NPN-Darl	Sw,Pow,600/300V,6A,100W,B>350	23a$	Org	BUW81,MJ10013..14,2SD605,2SD705..
2SD281..282	Si-NPN	-		Org	-
2SD283	Si-NPN	AF,Sw-Pow,120V,5A,25W,B>42	22a$	Nec	BD243C,BD539D,BD955,2SD961..
2SD284	Si-NPN	=2SD283:20MHz,B>25	22a$	Nec	BD243C,BD539D,BD955,2SD961..
2SD285	Si-NPN	=2SD283:100V	22a$	Nec	BD243C,BD539C,BD953,2SD613..
2SD286	Si-NPN	AF,Sw-Pow,180/100V,10A,100W	23a$	Nec	BD245E,2SC2607..08,2SC3263,2SD665,..
2SD287(A..C)	Si-NPN	AF,Sw-Pow,200/120V,10A,100W,8MHz	23a$	Nec	BD245F,2SC2607..08,2SC3263,2SD665..
2SD288	Si-NPN	AF,Sw-Pow,80V,3A,20W,35MHz	17j$	Nec,Mic	2SC3252,(BD241B,BD537,BD937,..)
2SD289	Si-NPN	=2SD288	17j$	Nec,Mic	2SC3252,(BD241B,BD537,BD937,..)
2SD29	Si-NPN	=2SD28:70/60V	22a$	Son	BD241B,BD537,BD937,2SD712..
2SD290	Si-NPN	AF,Sw-Pow,80V,5A,23W,10MHz	22a$	Son	BD243B,BD539B,BD951,2N4233A..
2SD291	Si-NPN	AF,Sw-Pow,70/40V,3A,18W,4MHz	22a$	Son	BD241A,BD537,BD937,2N4232..33..
2SD292	Si-NPN	=2SD291:70/55V	22a$	Son	BD241A,BD537,BD937,2N4232..33..
2SD293	Si-NPN	Sw,Pow,800/400V,10A,125W,B>14	23a$	Org	BUS12(A),BUW26,BUW35..36,BUX81,..
2SD294	Si-NPN	=2SD293:B>28	23a$	Org	BUS12(A),BUW26,BUW35..36,BUX81,..
2SD295	Si-NPN	Sw,Pow,800/400V,30A,200W,B>15	68a$	Org	2SC2204,2SC2977
2SD296	Si-NPN	=2SD295:B>30	68a$	Org	2SC2204,2SC2977
2SD297	Si-NPN	Sw,Pow,150/80V,3A,25W,40MHz	22a$	Nec	BD241D,2N3441,2SC2516,2SD772(A,B),..
2SD299	Si-NPN	TV-HD,1500V,5A,16W(Tc=90°),B>2	23a$	Matsushita	BU208(A),BU706,2SC2928,2SD820..
2SD30	Ge-NPN	AF-Dr/Out,25V,0,2A,0,3W	2ao	Sanyo	AC127,AC176(K),AC187(K),2SD72
2SD300	Si-NPN	=2SD299:B>3	23a$	Mat	BU208(A),BU706,2SC2928,2SD820..
2SD301(F)	Si-NPN-Darl	AF,Sw-Pow,80V,10A,50W,B=2S00	23a$	Fui	BDV65A,BDX83B,BDX85B,MJ3001..
2SD302..309	Si-NPN	-		Org	-
2SD31	Ge-NPN	AF,25V,0,125A,0,125W,B=50	2a	Mat	AC127,AC176,AC187,2SD30,2SD72
2SD310	Si-NPN	Sw,Pow,800/400V,15A,150W,B>15	23a$	Org	BUS13(A),BUW45..46,BUX48(A..C)
2SD311	Si-NPN	=2SD310:B>30	23a$	Org	BUS13(A),BUW45..46,BUX48(A..C)
2SD312	Si-NPN	Sw,Pow,800/600V,0,5A,25W(Tc=100°)	23a$	Matsushita	2SC3151
2SD313	Si-NPN	AF,Sw-Pow,60V,3A,30W,8MHz	17j$	Say,Mic	BD241A,BD535,BD539A,BD935..
2SD314	Si-NPN	=2SD313	17j$	Say,Mic	BD241A,BD535,BD539A,BD935..
2SD315	Si-NPN	=2SD313:4A,35W	22a$	Sanyo	BD243A,BD535,BD539A,2N4232..33A,..
2SD316(-1,-2)	Si-NPN	AF,Sw-Pow,80..100V,7A,80W,12MHz	23a$	Son	BD245C,BDV95,BDX95,2N5632..33..
2SD317	Si-NPN	AF,Sw-Pow,60V,3A,25W	17j$	Mat	BD241A,BD535,BD935,2N4232..33..
2SD317A	Si-NPN	=2SD317:80V	17j$	-	BD241B,BD537,BD937,2N4233..
2SD318	Si-NPN	=2SD317	17j$	Mat	→2SD317
2SD318A	Si-NPN	=2SD318:80V	17j$	-	→2SD317A
2SD319(Z)	Si-NPN	AF,Sw-Pow,CTV,110V,10A,100W,1MHz	23a$	Mat	BD317,2N3055,2N5632..33,2SD426..
2SD32	Ge-NPN	=2SD31:B=90	2a	Mat	AC127,AC176,AC187,2SD30,2SD73
2SD320	Si-NPN	Sw,Pow,300/230V,2A,50W	23a$	Sanyo	2SC1463,2SC2809,2SD632
2SD321	Si-NPN	Sw,Pow,250V,6A,60W,8MHz	23a$	Matsushita	BU606..608,BUX18(A..C),2SD1154..
2SD322	Si-NPN	AF,Sw-Pow,120/80V,7A,80W	23a$	Nec	BD245D,2N3442,2SD551,2SD731..733..
2SD323	Si-NPN	=2SD322:150/100V	23a$	Nec	BD245D,2N3442,2SD551,2SD731..733..
2SD324	Si-NPN	Vid-Pow,300V,0,1A,10W(Tc=70°)	22a$	Mat	2SC1505..1507,2SC1755..1757,2SC1819,..
2SD325	Si-NPN	AF,Sw-Pow,35V,1,5A,10W,8MHz	17j$	Sanyo	BD239,BD533,BD933,2SC1398..
2SD326	Si-NPN	Sw,Pow,330/220V,1A,23W,6,5MHz	22a$	Son	TIP47..50,2SC782,2SC867,2SD860..
2SD327	Si-NPN	GenP,40V,0,5A,0,25W,120MHz	7c	Nec,Mic	BC337,BC635,BC637,2SC3377..
2SD328(S)	Si-NPN	AF,Sw,100V,1A,0,8W,50MHz	2a$	Nec	BC141,2N1990,2N2102,2N2405..
2SD329	Si-NPN	AF,Sw,70V,1A,0,8W,30MHz,-/6,5µS	2a$	Fui	BC140..141,2N1990,2N2102,2N2405..
2SD33	Ge-NPN	AF,20V,0,05A,0,15W	2a	Fui	AC127,2SD30
2SD330	Si-NPN	AF,Sw-Pow,50V,2A,20W,8MHz	17j$	Say,Mic	BD239,BD241,BD535,BD935..
2SD331	Si-NPN	=2SD330	17j$	Say,Mic	BD239,BD241,BD535,BD935..
2SD332	Si-NPN	AF,Sw-Pow,130V,7A,65W,30MHz	23a$	Sanyo	BD245D,2N3442,2SD551,2SD731..733..
2SD333	Si-NPN	-		Sanyo	-
2SD334	Si-NPN	AF,Sw-Pow,110V,6A,75W	23a$	Mat	BD245C,2N3442,2SD551,2SD731..733..
2SD334A	Si-NPN	=2SD334:130V	23a$	-	BD245D,2N3442,2SD551,2SD731..733..
2SD335	Si-NPN	AF,Sw-Pow,80V,3A,30W	23a$	Nec	BD245B,BDV93,2N4915,2SD895..896..
2SD336	Si-NPN	GenP,AF-Dr/Out,40V,0,5A,0,75W	7co	Nec	BC337,BC635,BC637,2SC3377..
2SD337	Si-NPN	-		Son	-
2SD338-1,-2	Si-NPN	AF,Sw-Pow,-1=70V,-2=90V,7A,60W,>3MHz	23a$	Son	BD245C,BDV95,BDX95,2N5632..34..
2SD339-1,-2	Si-NPN	=2SD338:-1=90V,-2=110V,10A,80W	23a$	Son	BD245C,BDV95,BDX95,2N5632..34..
2SD34	Ge-NPN	AF,20V,0,15A,0,25W	1a	Fui	AC127,AC176,AC187,2SD30,2SD72
2SD340-1,-2)	Si-NPN	=2SD338:-1=110V,-2=140V,12A,100W	23a$	Son	BD745E,2N3442,2SD551,2SD733..
2SD341(H)	Si-NPN	AF,Sw-Pow,100V,15A,115W,>0,8MHz	23a$	Hit	BD317,BDW10,2N3055,2SD1105..

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2SD342	Si-NPN	AF,Sw-Pow,70/40V,3A,35W	17j$	Son	BD241A,BD537,BD937,2SC3179..
2SD343	Si-NPN	=2SD342	17j$	Son	→2SD342
2SD344	Si-NPN	=2SD342:70/55V	17j$	Son	BD241A,BD537,BD937,2SC3179..
2SD345	Si-NPN	=2SD342:70/55V	17j$	Son	→2SD344
2SD346	Si-NPN	AF,Sw-Pow,60V,5A,25W	17j$	Son	BD243A,BD543A,BD949,2SD1505..
2SD347	Si-NPN	=2SD346	17j$	Son	→2SD346
2SD348	Si-NPN	TV-HD,1500/400V,7A,50W	23a$	Sanyo	BU2508A,BU908,2SC3027..3028..
2SD349	Si-NPN	AF,30V,0,05A	35a	NEC	BC846..848,BCW31..33,2SC1622..
2SD35	Ge-NPN	AF,20V,0,06A,0,083W	37a	Mat	AC127,2SD72
2SD350(A)	Si-NPN	TV-HD,1500/700V,5A,22W(Tc=90°)	23a$	Matsushita	BU208A,BU706,2SC2928,2SD954..
2SD351	Si-NPN	Sw,Pow,650/270V,5A,80W,40MHz	23a$	Mat	BU326(A),BU426(A),2SC2962,2SC3092..
2SD352	Ge-NPN	AF,32V,1A,0,22W	2a	Mat	AC176
2SD353	Si-NPN	AF,Sw-Pow,TV-VD,150V,2A,60W,8MHz	23a$	Sanyo	2SC1195,2SC2809,2SD1136,2SD1159..
2SD354	Si-NPN	-		Ful	-
2SD355	Si-NPN	GenP,30V,1A,0,8W,100MHz	7b	Mit	BC337..338,BC635,BC637,2SD1225..
2SD356	Si-NPN	AF,Sw-Pow,90V,0,8A,10W,70MHz	17j$	Mit,Mic	2SC1913(A),2SC2275(A),2SC2591..92..
2SD357	Si-NPN	=2SD356:110V	17j$	Mit	2SC1913(A),2SC2275(A),2SC2591..92..
2SD358	Si-NPN	=2SD356:130V	17j$	Mit	2SC1913(A),2SC2275(A),2SC2591..92..
2SD359	Si-NPN	AF,Sw-Pow,40V,2A,10W,70MHz	17j$	Mit,Mic	2SC1398,2SC3252
2SD36	Ge-NPN	AF,20V,0,06A,0,083W	37a	Mat	AC127,2SD72
2SD360	Si-NPN	AF,Sw-Pow,40V,2A,10W,70MHz	17j$	Mit,Mic	2SC1398,2SC3252
2SD361	Si-NPN	AF,Sw-Pow,60V,1,5A,10W,70MHz	17j$	Mit	2SC1398,2SC3252
2SD362	Si-NPN	Sw,Pow,150/100V,5A,40W,15MHz	22a$	Nec	BU406..409,MJE15030,2SD772(A,B)..
2SD363	Si-NPN	Sw,Pow,250/200V,30A,200W,<2/10,5µS	68a$	Nec	2SD374
2SD363A	Si-NPN	=2SD363:350/300V	68a$	-	2SD374
2SD364	Si-NPN	=2SD363:450/400V	68a$	Nec	2SD374
2SD365	Si-NPN	AF,Sw-Pow,60V,3A,25W,>3MHz	17j$	Mat,Mic	BD241A,BD535,BD935,2SC3179..
2SD365A	Si-NPN	=2SD365:80V	17j$	-	BD241B,BD537,BD937,2SC3179..
2SD366(A)	Si-NPN	=2SD365(A)	17j$	Mat,Mic	→2SD365(A)
2SD367	Ge-NPN	AF,25V,0,3W,0,15W	2a	Mat	AC127,AC176,AC187,2SD72,2SD352
2SD368	Si-NPN	TV-HD,1300/400V,5A,50W	23a$	Sanyo	BU207..208A,BU706,BU903,2SC2928..
2SD369	Si-NPN	AF,Sw-Pow,80V,10A,100W,2MHz	23a$	Tos	BD315,BDW21C,2N3055,2N5632..34..
2SD37	Ge-NPN	AF,30V,0,05A,0,15W	2a	Fui	AC127,2SD30
2SD370	Si-NPN	AF,Sw-Pow,110V,8A,80W	23a$	Tos	BD245C,BDS50,2N3055,2N5633..34..
2SD371	Si-NPN	AF,Sw-Pow,100V,6A,50W,5MHz	23a$	Tos	BD245C,BDV95,BDX95,2SD895..896..
2SD372	Si-NPN	Sw,Pow,150/100V,30A,200W,0,3/2µS	68a$	Nec	2SD363
2SD373	Si-NPN	=2SD372:250/200V	68a$	Nec	2SD363
2SD373A	Si-NPN	=2SD372:350/300V	68a$	-	-
2SD374	Si-NPN	=2SD372:450/400V	68a$	Nec	-
2SD375	Si-NPN	Sw,Pow,150/100V,10A,100W,15MHz	23a$	Nec	BUW70,BUX17(A..C),BUX43,BUY18..
2SD376	Si-NPN	=2SD375:250/200V	23a$	Nec	BUW72,BUX17(A..C),BUX43,BUY18..
2SD376A	Si-NPN	=2SD375:350/300V	23a$	-	BUW72,BUX14,BUX17A..C,BUX43..
2SD377	Si-NPN	=2SD375:450/400V	23a$	Nec	BUW72,BUX14,BUX17C,2SC3046..
2SD378	Si-NPN	AF,Sw,100V,2A,1W	2a$	Nec	BCX40,BSS15,BSVB4,2NS320..
2SD379	Si-NPN	AF,Sw-Pow,80V,5A,60W,10MHz	23a$	Mat	BD245B,BD313,BDV93,BDX93..
2SD38	Ge-NPN	AF,30V,0,15A,0,25W	1a	Fui	AC127,AC176,AC187,2SD30,2SD72
2SD380(A)	Si-NPN	TV-HD,1500/700V,5A,50W(Tc=75°)	23a$	Matsushita	BU208(A),BU706,2SC2928,2SD954..
2SD381	Si-NPN	AF,Sw-Pow,130V,1,5A,20W,45MHz	17j$	Nec	2SC2238(A),2SC2275(A),2SD608(A)..
2SD382	Si-NPN	=2SD381	17j$	Nec	→2SD381
2SD383	Si-NPN	Sw,Pow,300/300V,5A,100W	23a$	Hitachi	BU606..608,BUX16A..C,BUY35..
2SD384	Si-NPN-Darl	AF,Sw-Pow,80V,7A,30W,B>1500,<3/9µS	22a$	Shi	BD647,BD899,BDW73B,BDX53B..
2SD385	Si-NPN-Darl	=2SD384:100V	22a$	Shi	BD649,BD901,BDW73C,BDX53C..
2SD386(A)	Si-NPN	TV-VD,200/120V,3A,25W,8MHz	17j$	Sanyo	BD241F,2SD772A,B
2SD387(A)	Si-NPN	=2SD386(A):2A	17j$	Sanyo	BD239F,2SC2660,2SD610,2SD760,2SD1138
2SD388	Si-NPN	AF,Sw-Pow,150V,8A,80W,9MHz	23a$	Nec	BD245D,2N3442,2SD551,2SD732..733..
2SD389	Si-NPN	AF,Sw-Pow,60V,3A,25W	17j$	Mat	BD241A,BD535,BD935,2SC3179..
2SD389A	Si-NPN	=2SD389:80V	17j$	-	BD241B,BD537,BD937,2SC3179..
2SD390(A)	Si-NPN	=2SD389(A)	17j$	Mat	→2SD389(A)
2SD391	Si-NPN	-		Sanyo	-
2SD392	Si-NPN	GenP,20V,0,3A,0,3W,150MHz	7b	Mit	BC337..338,BC635,BC637,2SC3377..
2SD393	Si-NPN	Sw,Pow,500/350V,6A,100W	23a$	Mitsubishi	BU326(A),BU426(A),BUX15,2SC3041,..
2SD394	Si-NPN	Sw,Pow,700/400V,6A,100W	23a$	Mit	BU326(A),BU426(A),BUX47,2SC3092,..
2SD395	Si-NPN	Sw,Pow,700/400V,8A,100W	23a$	Mit	BU526(A),BUW26,BUW35..36,2SC3049..
2SD396	Si-NPN	Sw,Pow,700/300V,15A,125W,<15/40µS	23a$	Hit	BUS13(A),BUW45..46,BUX48(A..C)..

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2SD397..399	Si-NPN	-		Sanyo	-
2SD400(MP)	Si-NPN	GenP,Lo-sat,25V,1A,0,9W,180MHz	7c(9mm)	Sanyo	2SC4483..85,2SD1207
2SD400P1,P2	Si-NPN	=2SD400(MP):1W	7co	-	(BD505,BD515,BD525,2SC2194,..)
2SD401(A)	Si-NPN	TV-VD,200V,2A,20(A=25)W,5MHz	17j$	Nec	BD239F,2SC2660,2SD610,2SD1138..
2SD402(A)	Si-NPN	=2SD401(A)	17j$	Nec	→2SD401(A)
2SD403	Si-NPN	-		Tos	-
2SD404(G)	Si-NPN	AF,Sw-Pow,50V,6A,40W	17j$	Tos	BD243A,BD797,BD805,2SD1442A..
2SD405	Si-NPN-Darl	AF,Sw,70V,2A,1W,B>2000,0,4/3µS	2a$	Nec	2SC1879,2SC1888,2SD614..615,2SD688
2SD406	Si-NPN-Darl	=2SD405:100V	2a$	Nec	2SC1879,2SD614..615,2SD688
2SD407	Si-NPN-Darl	AF,Sw-Pow,100V,5A,25W,B=4000,1,7/6µS	2a$	Nec	(BD649,BD901,BDW23C,BDW63C,..)
2SD408	Si-NPN-Darl	=2SD407:150V,hFE=3000	2a$	Nec	(2SD830,2SD1128,2SD1169,2SD1590,..)
2SD409	Si-NPN-Darl	=2SD407:30W	22a$	Nec	BD649,BD901,BDW23C,BDW63C..
2SD41	Si-NPN	AF,Sw-Pow,80V,10A,200W	23a$	Tos	BD315,BD317,2N3772,2N5629..31..
2SD410	Si-NPN-Darl	=2SD407:150V,30W,B=3000	22a$	Nec	2SD830,2SD1128,2SD1169,2SD1590..
2SD411	Si-NPN-Darl	AF,Sw-Pow,100V,10A,80W,B=4000,1/7µS	23a$	Nec	BDV65B,BDW83C,BDX83C,BDX85C..
2SD412	Si-N-Darl+Di	AF,Sw-Pow,150/100V,15A,100W,B=4000	23a$	Nec	2SD1296,2SD1299
2SD413	Si-NPN	Sw,Vid,200/200V,0,5A,0,8W,25MHz	2a$	Fui	2SD576,2SD624,(BF757..759,MPSU10..)
2SD414	Si-NPN	AF-Pow,120/80V,0,8A,10W,45MHz	14h$	Nec	2SC2690(A),2SD1382,2SD1563(A)
2SD415	Si-NPN	=2SD414:120/100V	14h$	Nec	2SC2690(A),2SD1382,2SD1563(A)
2SD416	Si-NPN	TV-HD,1500/400V,7A,50W	23a$	Sanyo	BU508A,BU908,2SC3027..28,2SC3686
2SD417	Si-NPN	Sw,Pow,250/200V,7A,75W,30MHz	23a$	Fujitsu	BU606..608,BUX18(A..C),2SD1154..
2SD418	Si-NPN	TV-HD,1000/500V,5A,80W	23a$	Matsushita	BU207..208(A),BU706,2SC1413,2SC3672
2SD419	Si-NPN-Darl	AF,Sw-Pow,100/80V,7A,40W,6MHz,B=2500	22a$	Sak	BD649,BD901,BDW73C,BDX53C..
2SD420	Si-NPN-Darl	=2SD419:120/100V	22a$	Sak	BD651,BDT21,BDW73D,BDX53E..
2SD421	Si-NPN-Darl	=2SD419:140V	22a$	Sak	BDX53E,F,2SD1386,2SD1590..1591
2SD422	Si-NPN	Sw,Pow,250/200V,4A,30W,30MHz	22a$	Fui	BU406..409,2N6233..35,2SC2767..
2SD423	Si-NPN	Sw,Pow,250/200V,4A,30W,30MHz	22a$	Fui	BU406..409,2N6233..35,2SC2767..
2SD424	Si-NPN	AF-Pow,180V,15A,150W,5MHz	23a$	Toshiba	BDW12,MJ15015,2N3773,2SC2607..2608..
2SD425	Si-NPN	AF-Out,140V,12A,100W	23a$	Toshiba	BDW12,BDY54,2SD551,2SD1047..
2SD426	Si-NPN	AF-Out,120V,12A,100W,5MHz	23a$	Toshiba	BDW10,2SD551,2SD733,2SD1105..
2SD427(S)	Si-NPN	AF-Out,120V,8A,80..100W,5MHz	23a$	Toshiba	BD550,2N5633..34,2SD551,2SD733..
2SD428	Si-NPN	AF-Out,100V,7A,60W,7MHz	23a$	Toshiba	BD245C,BDV95,BDX95,2N5632..33..
2SD429	Si-NPN	Sw,Pow,800/400V,15A,100W,<20/15µS	23a$	Hit	BUS13(A),BUW45..46,BUX48(A..C)..
2SD43	Ge-NPN	AF,25V,0,05A,0,11W	2a	Tos	AC127,2SD30
2SD430	Si-NPN	Sw,Pow,120/80V,5A,50W,15MHz	23a$	old	BD245D,2N4347,2N5759,2SD896..
2SD431	Si-NPN	Sw,Pow,120/80V,7A,60W,20MHz	23a$	old	BD245D,2N4348,2N5633..34,2SD718..
2SD432	Si-NPN	Sw,Pow,130/100V,10A,100W,15MHz	23a$	old	BD245D,2N3442,2SD551,2SD733..
2SD433	Si-NPN	Sw,Pow,250V,10A,100W,15MHz	23a$	old	BUX17(A..C),2SC1586,2SD555,2SD583,..
2SD434	Si-NPN	Sw,Pow,200/200V,20A,200W	23a$	old	BUV11..12,BUW58,BUW73,BUX11..12
2SD435	Si-NPN	=2SD434:300/300V	23a$	old	BUV12,BUV24,BUW73,BUX12,BUX24
2SD436	SI-NPN	=2SD434:400/400V	23a$	old	BUV24,BUX24,2SC3085
2SD437(W)	Si-NPN	Sw,Pow,600/350V,10A,80W,2,5MHz	23a$	Sanyo	BUW12(A),BUW25..26,BUX80,2SC3046..
2SD438	Si-NPN	100V,0.7A,0.9W,100MHz	-		-
2SD438(MP)	Si-NPN	GenP,Lo-sat,100V,0,7A,0,9W,100MHz	7c(9mm)	Sanyo	2SC4488,2SC4489,2SD667,2SD1812
2SD439	Si-NPN	AF,Sw-Pow,Lo-sat,20V,1,2A,8W,150MHz	14h$	Sanyo	BD135,BD226,BD375,2SD1380..
2SD43A	Ge-NPN	=2SD43:45V,0,15A	2a	-	-
2SD44	Ge-NPN	AF,30V,0,05A,0,08W	2a	Tos	AC127,2SD30
2SD440	Si-NPN	-		Sanyo	-
2SD441..444	Si-NPN	-		Org	-
2SD445	Si-NPN-Darl	Sw,Pow,350/300V,4A,60W,B>350	23a$	Org	BUX28..29,2SD650,2SD706,2SD1043..
2SD446..456	Si-NPN	-		Org	-
2SD45	Si-NPN	AF,Sw-Pow,150/100V,5A,50W,20MHz	23a$	Son	BD245D,BDX11,2N3442,2SD551,2SD732,..
2SD457	Si-NPN	Sw,Pow,250/200V,55A,200W	68a$	Nec	-
2SD45B	Si-NPN	Sw,Pow,600/400V,5A,80W	23a$	Mat	BU326(A),BU426(A),BUW11(A),2SC2962..
2SD459	Si-NPN-Darl	AF,Sw-Pow,80V,7A,50W,B>1500,3/9µS	17j$	Shi	BD647,BD899,BDW73B,BDX53B..
2SD46	Si-NPN	=2SD45:150/75V	23a$	Son	BD245D,BDX11,2N3442,2SD551,2SD732,..
2SD460	Si-NPN-Darl	=2SD459:100V	17j$	Shi	BD649,BD901,BDW73C,BDX53C..
2SD461	Si-NPN	Sw,Pow,250/250V,3A,80W,1MHz	23a$	Hitachi	BU606..608,BUX16(A..C),2SD632..
2SD462	Si-NPN	-		Son	-
2SD463	Si-NPN-Darl	AF,Sw-Pow,80V,7A,80W,B=3000,<10/16µS	23a$	Shi	BDX63A,TIP141..142,2SD628..629..
2SD464	Si-NPN-Darl	=2SD463:100V	23a$	Shi	BDX63B,TIP142,2SD628..629,2SD1230..
2SD465	Si-NPN-Darl	Sw,Pow,500/400V,50A,400W,B>150	?74	Shi	-
2SD466	Si-NPN-Darl	=2SD465:600/450V	?74	Shi	-
2SD467	Si-NPN	GenP,25V,0,7A,0,5W,280MHz	7c	Hit	(BC337..338,BC635,BC637,2SD1225..)

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2SD468	Si-NPN	=2SD467: 1A, 0,9W, 190MHz	7c(9mm)	Hit	2SC2236, 2SC4483, 2SD1207, 2SD1331..
2SD469	Si-NPN	Sw, Pow, 150V, 10A, 100W, 18MHz, 0,5/3,5µS	23a$	NEC	BD245D, 2N3442, 2SD551, 2SD733..
2SD47	Si-NPN	=2SD45: 100/50V	23a$	Son	BD245C, BDV95, BDX95, 2N5632..33..
2SD470(-B)	Si-NPN	TV-HD, 1600/700V, 1A, 15W	22a$	Mat	BU505, 2SD948, 2SD1575
2SD471	Si-NPN	GenP, 30V, 1A, 1W, 130MHz	9b	NEC	BC337..338, BC635, BC637, 2SD1225..
2SD472(H)	Si-N-Darl+Di	AF, Sw-Pow, 150V, 10A, 80W, B>1000, 2/9µS	23a$	Hit	BDV67D, 2SD922, 2SD1296, 2SD1299
2SD473(H)	Si-N-Darl+Di	=2SD472: 100V, 15A, 100W	23a$	Hit	BDV67A, BDW83C, BDX67B, MJ4035..
2SD474(K)	Si-NPN	GenP, 30V, 0,1A, 0,05W, >100MHz	9b	Hitachi	BC168, BC183, BC238, BC548, 2SD767..
2SD475(A)	Si-NPN	AF, Sw-Pow, 70V, 4A, 40W, 7MHz	17j$	Hit	BD243B, BD537, BD539B, BD951..
2SD476(A)	Si-NPN	=2SD475(A)	17j$	Hit	→2SD475(A)
2SD477	Si-NPN	AF, Sw-Pow, 200/150V, 2A, 30W	17j$	Hit	BD239F, 2SC2660, 2SD610, 2SD760, 2SD1138
2SD478	Si-NPN	=2SD477	17j$	Hit	→2SD477
2SD479	Si-NPN-Darl	AF, Sw-Pow, 40V, 4A, 40W, B=6000	14h$	Mot	BD675, BD775, 2N6037..6039..
2SD48(N)	Si-NPN	AF, Sw-Pow, 100V, 3A, 20W	2a$	Ful	(BD241C, BD539C, BD939, 2SD712,..)
2SD480	Si-NPN-Darl	=2SD479: 60V	14h$	Mot	BD677, BD777, 2N6038..6039..
2SD481	Si-NPN-Darl	=2SD479: 80V	14h$	Mot	BD679, BD779, 2N6039
2SD482	Si-NPN	Vid-Pow, 275/250V, 0,5A, 20W	14h$	Mot	MJE340, 2N5655, 2SC2752, 2SC2899..
2SD483	Si-NPN	=2SD482: 325/300V	14h$	Mot	MJE340, 2N5656, 2SC2752, 2SC2899..
2SD484	Si-NPN	=2SD482: 375/350V	14h$	Mot	BD410, 2N5657, 2SC2899, 2SC3051..
2SD485	Si-NPN	AF, Sw-Pow, 40V, 4A, 40W	14h$	Mot	BD185, BD437, BD785, 2N5190..92..
2SD486	Si-NPN	=2SD485: 60V	14h$	Mot	BD187, BD439, BD787, 2N5191..92..
2SD487	Si-NPN	=2SD485: 80V	14h$	Mot	BD189, BD441, BD787, 2N5192..
2SD488	Si-NPN	AF, Sw-Pow, 40V, 3A, 30W	14h$	Mot	BD175, BD185, BD437, 2N4921..23..
2SD489	Si-NPN	=2SD488: 60V	14h$	Mot	BD177, BD187, BD439, 2N4922..23..
2SD49	Si-NPN	AF, Sw-Pow, 100V, 3A, 18W	22a$	Son	BD241C, BD539C, BD939, 2SD877..
2SD490	Si-NPN	=2SD488: 80V	14h$	Mot	BD179, BD189, BD441, 2N4923..
2SD491	Si-NPN	AF, Sw-Pow, 70V, 10A, 90W	16h$	Mot	BD207, MJE3055
2SD492	Si-NPN	=2N3055	23a$	Mot	→2N3055
2SD493	Si-NPN	AF, Sw-Pow, 60V, 5A, 75W	16h$	Mot	BD199, 2N5977..5979
2SD494	Si-NPN	=2SD493: 80V	16h$	Mot	2N5978..5979
2SD495	Si-NPN	=2SD493: 100V	16h$	Mot	2N5979
2SD496	Si-NPN-Darl	AF, Sw-Pow, 60V, 8A, 75W, B=3000	16h$	Mot	(BDV65(A..C), TIP140..142)
2SD497	Si-NPN-Darl	=2SD496: 80V	16h$	Mot	(BDV65A..C, TIP141..142)
2SD498	Si-NPN-Darl	=2SD496: 100V	16h$	Mot	(BDV65B..C, TIP142)
2SD499	Si-NPN	AF, Sw-Pow, 60V, 8A, 90W	16h$	Mot	BD207, 2N5983..5985
2SD50(N)	Si-NPN	AF, Sw-Pow, 100V, 6A, 50W	23a$	Hit,Ful	BD245C, BDV95, BDX95, 2N5632..33..
2SD500	Si-NPN	=2SD499: 80V	16h$	Mot	2N5984..5985
2SD501	Si-NPN	=2SD499: 100V	16h$	Mot	2N5985
2SD502	Si-NPN-Darl	AF, Sw-Pow, 60V, 8A, 100W, B=3000	23a$	Mat	BDV65(A..C), BDX83A..C, BDX85A..C..
2SD503	Si-NPN-Darl	=2SD502: 80V	23a$	Mot	BDV65A..C, BDX83B..C, BDX85B..C..
2SD504	Si-NPN-Darl	AF, Sw-Pow, 60V, 12A, 150W, B=3000	23a$	Mot	BDV65(A..C), BDW83A..D, BDX87A..C..
2SD505	Si-NPN-Darl	=2SD504: 80V	23a$	Mot	BDV65A..C, BDW83B..D, BDX87B..C..
2SD506	Si-NPN-Darl	=2SD504: 100V	23a$	Mot	BDV65B..C, BDW83C..D, BDX87C..
2SD507	Si-NPN	Sw, Pow, 90V, 250A, 625W, <5/10µS	53b$	Mit	-
2SD508	Si-NPN	=2SD507: 110V	53b$	Mit	-
2SD509	Si-NPN	=2SD507: 130V	53b$	Mit	-
2SD51(N)	Si-NPN	AF, Sw-Pow, 100V, 6A, 50W	23a$	Son,Tos	BD245C, BDV95, BDX95, 2N5632..33..
2SD510	Si-NPN	=2SD507: 150V	53b$	Mit	-
2SD511	Si-NPN	Sw, Pow, 90V, 250A, 625W, <5/10µS	53b$	Mit	-
2SD512	Si-NPN	=2SD511: 110V	53b$	Mit	-
2SD513	Si-NPN	=2SD511: 130V	53b$	Mit	-
2SD514	Si-NPN	Sw, Pow, 90V, 250A, 625W, <5/10µS	53b$	Mit	-
2SD515	Si-NPN	=2SD514: 110V	53b$	Mit	-
2SD516	Si-NPN	AF, Sw-Pow, 20V, 1,5A, 5W, B=100..500	14h$	Nec	BD135, BD165, BD226, BD233..
2SD517	Si-NPN	TV-HD, 1500/700V, 3A, 16W(Tc=90°)	23a$	Matsushita	BU208A, BU706, 2SC3023..24, 2SD1495
2SD518	Si-NPN	Sw, Pow, 220/200V, 4A, 30W, 30MHz	22a$	Fui	BU406..409, 2SC2767, 2SD422..423..
2SD519	Si-NPN	Sw, Pow, 600/400V, 10A, 100W, <3,5/6,5µS	23a$	Fui	BUW25..26, BUW35..36, 2SC3046..
2SD51A(AN)	Si-NPN	=2SD51: 150V	23a$	-	BD245D, BDX11, 2N3442, 2SD551, 2SD732,..
2SD52(N)	Si-NPN	AF, Sw-Pow, 100V, 6A, 80W	23a$	Fui,Sak,Tos	BD245C, BDV95, BDX95, 2N5632..33..
2SD520	Si-NPN-Darl	Sw, Pow, 600/400V, 7A, 100W, B>350	23a$	Mit	BUW81(A), 2SD528, 2SD605, 2SD705..
2SD521	Si-NPN-Darl	Sw, Pow, 700/450V, 8A, 100W, B>200	23a$	Mit	BUT50P, BUW81A, 2SC3030..3033
2SD522	Si-NPN	AF, Sw-Pow, 100V, 10A, 100W	23a$	Tos	BD317, BDW21C, 2N3055, 2N5632..34..
2SD523	Si-N-Darl+Di	AF, Sw-Pow, 80V, 7A, 50W, B>2000	23a$	Tos	BDV65A, BDX63A, MJ1001, 2N6056..
2SD524	Si-N-Darl+Di	AF, Sw-Pow, 80V, 15A, 100W, B>2000	23a$	Tos	BDW83B, BDX67A, MJ4034..4035..

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2SD525	Si-NPN	AF-Out, 100V, 5A, 40W, 12MHz	17j$	Tos	BD243C, BD543C, BD953, 2SD613..
2SD526	Si-NPN	AF-Pow, 80V, 4A, 30W, >3MHz	17j$	Mic,Tos	BD243B, BD537, BD951, 2SD1236L..
2SD527	Si-NPN	-		Tos	-
2SD528(H)	Si-NPN-Darl	Sw, Pow, 600/500V, 8A, 100W, B>350	23a$	Hit	BUW81(A), 2SD520..521, 2SD605, 2SD705
2SD529	Si-NPN	Sw, Pow, 850/320V, 5A, 85W, 4MHz	23a$	Sony	BU326A, BU426A, BUS11(A), 2SC315S..
2SD52A(AN)	Si-NPN	=2SD52: 130V	23a$	-	BD245D, BDX11, 2N3442, 2SD551, 2SD732,..
2SD53(N)	Si-NPN	AF, Sw-Pow, 90V, 10A, 100W	23a$	Fui,Tos	BD245C, BDV95, BDX9S, 2N5632..33..
2SD530	Si-NPN-Darl	AF, Sw-Pow, 100V, 10A, 50W, B>750	23t(3pins)	Fui	-
2SD531(-1,-2)	Si-NPN	AF, Sw-Pow, 100V, 5A, 43W, 9MHz	17j$	Son	BD243C, BD539C, BD953, 2SD613..
2SD532	Si-NPN	Sw, Pow, 200/70V, 7A, 70W, 9MHz	23a$	Sony	BU606..608, 2SC2262, 2SC2769, 2SD751,..
2SD533	Si-NPN	Sw, Pow, 270/90V, 10A, 100W, 8MHz	23a$	Sony	BUX17(A..C), BUX42..43, 2SC2961..
2SD534	Si-NPN	AF, Sw-Pow, 110V, 12A, 100W, 5MHz	23a$	Son	BD317, BDW10, 2N3055, 2N5629..31..
2SD535	Si-NPN	Sw, Pow, 250/120V, 12A, 150W, 1,5/8µS	23a$	NEC	BUW74, BUX41..42, MJ15022, 2SD583..
2SD536	Si-NPN	Sw, Pow, 200/200V, 10A, 100W, -/1,8µS	23a$	Fujitsu	BUX17(A..C), BUX42..43, 2SC2769..
2SD537	Si-NPN	=2SD536: 200/150V	23a$	Fui	BUX17(A..C), BUX42..43, 2SC2769..
2SD538(A)	Si-NPN	Sw, Pow, 500/400V, 10A, 100..150W, 15MHz	23a$	Fujitsu	BUW25..26, BUW34..36, 2SC3046, 2SC4138..
2SD539(A)	Si-NPN	=2SD538(A): 400/350V	23a$	Fui	BUW24..26, BUW34..36, 2SC3046, 2SC4138..
2SD53A(AN)	Si-NPN	=2SD53: 130V	23a$	-	BD245D, BDX11, 2N3442, 2SD551, 2SD733,..
2SD54(N)	Si-NPN	AF, Sw-Pow, 100V, 10A, 150W	38a$	Fui,Tos	(BD249C, BD745C, 2SD1049)
2SD540	Si-NPN	Sw, Pow, 200/200V, 30A, 200W, 25MHz	68a$	Fui	2SC2249, 2SC2445, 2SC2940, 2SC3224..
2SD541	Si-NPN	=2SD540: 200/150V	68a$	Fui	2SC2249, 2SC2445, 2SC2940, 2SC3224..
2SD542	Si-NPN	Sw, Pow, 400/400V, 30A, 200W, 20MHz	68a$	Fui	2SC1302, 2SC1401, 2SC1470, 2SC2250..
2SD543	Si-NPN	=2SD542: 400/350V	68a$	Fui	2SC1302, 2SC1401, 2SC1470, 2SC2250..
2SD544(-1,-2)	Si-NPN	=2SD531-..	17j$	Son	→2SD531
2SD545(NP)	Si-NPN	GenP, Lo-sat, 25V, 1A, 0,5W, 180MHz	7c(9mm)	Say,Mic	2SC4483..85, 2SD1207, 2SD1247
2SD546	Si-NPN	Sw, Pow, TV-VD, 800/500V, 1A, 30W, 7MHz	22a$	Mat	BUV36(A), BUX84..85, 2SC1828, 2SC3352
2SD547	Si-NPN-Darl	Sw, Pow, 600/450V, 50A, 400W, 1/10,5µS	?74	Tos	-
2SD548	Si-NPN-Darl	Sw, Pow, 600/450V, 120A, 770W, 3/20µS	-	Tos	-
2SD549	Si-NPN-Darl	AF, Sw-Pow, 30V, 1,5A, 15W, B>4000	14h$	Tos	BD675, BD775, 2SD985..986, 2SD1379..
2SD55(N)	Si-NPN	AF, Sw-Pow, 100V, 20A, 200W	23a$	Tos	BDW30, BDY29, MJ802, 2N3772, 2SD797..
2SD550	Si-NPN	AF, Sw-Pow, 120V, 7A, 40W, 10MHz	22a$	Tos	BD243C, BD543D, MJ15028, 2SD866
2SD551	Si-NPN	AF, Sw-Pow, 150V, 12A, 100W, 15MHz	23a$	Tos	BD745E, 2SC1584, 2SD733, 2SD1047..
2SD552	Si-NPN	Sw, Pow, 220/180V, 15A, 150W, 4MHz, 1/4µS	23a$	Toshiba	BUX41, 2SC1586, 2SC2608, 2SC3263, 2SD583
2SD553	Si-NPN	Lo-sat, 70V, 7A, 40W, 10MHz, 0,2/3µS	17j$	Tos	2SC3254, 2SD1237L
2SD554	Si-NPN	Sw, Pow, 250V, 2A, 30W	22a$	Nec	BUX67(A..C), 2N3583..85, 2SD610..
2SD555	Si-NPN	Sw, Pow, AF-Pow, 250V, 10A, 200W, 15MHz	23a$	Nec	BUX17A..C, BUY18, 2SC1576, 2SD583..
2SD556	Si-NPN	Sw, Pow, 110V, 15A, 120W, 8MHz	23a$	Sak	BD745C, BDW10, 2N5630..31, 2SD1105..
2SD557	Si-NPN	=2SD556: 140V	23a$	Sak	BD745E, BDW10, 2N5631, 2SC2607..08..
2SD558	SI-NPN-Darl	AF, Sw-Pow, 90V, 2A, B>2000, 0,4/3µS	30j$	Nec	2SD1223, 2SD1520, 2SD1980
2SD55A(AN)	Si-NPN	=2SD55: 130V	23a$	-	BDW30, BDW32, BDY58
2SD56	Si-NPN	Sw, Pow, 220V, 3A, 30W	22a$	Son	D44Q3, TIP75(A..C), 2SC867A, 2SC2767,..
2SD560	Si-N-Darl+Di	AF, Sw-Pow, 150V, 5A, 30W, B=2k..15k	17j$	Nec	2SD830, 2SD1128, 2SD1169, 2SD1590..
2SD561..564	Si-NPN	-		Nec	-
2SD565	Si-N-Darl+Di	Sw, Pow, 400/400V, 10A, 100W, B>800	23a$	NEC	BU920..922, MJ10002..03, 2SD685..
2SD566..567	Si-NPN	-		Nec	-
2SD568	Si-NPN	AF, Sw-Pow, 100V, 7A, 40W	17j$	Nec	MJE15028, BD543B, BD799, BD809..
2SD569	Si-NPN	AF, Sw-Pow, 100V, 7A, 40W	17j$	Nec	MJE15028, BD543B, BD799, BD809..
2SD57	Si-NPN	AF, Sw-Pow, 30V, 3A, 20W	22a$	Mit	BD241, BD533, BD933, 2SD877..
2SD570	Si-NPN	AF, Sw-Pow, 70V, 4A, 30W, >3MHz	17j$	Mat,Mic	BD243A, BD537, BD951, 2SC3179..
2SD571	Si-NPN	GenP, 60V, 0,7A, 1W, 110MHz	9b	NEC	BC637, BC639, 2SD667, 2SD1226..
2SD572	Si-NPN-Darl	Sw, Pow, 500/400V, 15A, 150W, B>80	23a$	Shidengen	BU932, 2SD683, 2SD711(A)
2SD573	Si-NPN-Darl	=2SD572: 600/450V	23a$	Shi	2SD683, 2SD711A
2SD574(A)	Si-NPN-Darl	Sw, Pow, 120/120V, 30A, 400W, B>200	68a$	Shi	-
2SD575	Si-NPN	TV-HD, 1400/600V, 2,5A, 50W	23a$	Sanyo	BU205..206, 2SC1922, 2SD818..819..
2SD575L	Si-NPN	=2SD575: 1200/600V	23a$	-	BU204..206, 2SC1922, 2SD818..819..
2SD576	Si-NPN	Sw, Vid, 250V, 0,5A, 0,8W, 200MHz	2a$	Fui	BFQ38..40, 2NS010, (BF757..759..)
2SD577	Si-NPN	TV-HD, 1500V, 3A, 16W(Tc=90°)	23a$	Matsushita	BU208..209A, BU706, 2SC3023..24..
2SD578	Si-NPN-Darl	Sw, Pow, 500/140V, 8A, 100W, B>350	23a$	Hitachi	BU922, 2SD528, 2SD605, 2SD796..
2SD578(A)	Si-NPN	AF, Sw-Pow, 180V, 2A, 30W	17j$	Hit	BD239E, 2SC2660, 2SD760, 2SD1138..
2SD579	Si-NPN	AF, Sw-Pow, 100V, 4A, 40W	22a$	Hit	BD243C, BD539C, BD953, 2N3767..
2SD58	Si-NPN	=2SD57: 60V	22a$	Mit	BD241A, BD535, BD935, 2SD877..
2SD580	Si-NPN	AF, Sw-Pow, 60V, 1A, 20W, 1,2MHz	2a$	Fui	(BD137, BD167, BD228, BD235,..)
2SD581(A)	Si-NPN	AF, Sw-Pow, 150/100(A=/120)V, 7A, 60W	23a$	Hit	BDX11, 2SD732, 2SD751, 2SD1046..
2SD582(A)	Si-NPN	AF, Sw-Pow, 180/140(A=/160)V, 12A, 100W	23a$	Hit	BDW14, MJ15015, 2SC2607..08, 2SD424,..

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2SD583	Si-NPN	AF,Sw-Pow,250V,15A,150W	23a$	Hit	BUX41,MJ15022,MJ15024,2SC1586
2SD584	Si-NPN	-		Mit	-
2SD585	Si-NPN-Darl	AF,Sw-Pow,110V,7A,80W,B>1100	23a$	Mit	BDV65C,BDX63C,BDX65C,2SD1210
2SD586(A)	Si-NPN	AF,Sw-Pow,100V,5A,60W,15MHz	19j$	Nec	2SC2276,2SD848(A),2SD883(A)
2SD587(A)	Si-NPN	AF,Sw-Pow,120V,6A,70W,17MHz	19j$	Nec	2SC2276,2SB848(A),2SB883A
2SD588(A)	Si-NPN	AF,Sw-Pow,150V,7A,80W	19j$	Nec	-
2SD589	Si-NPN	TV-HD,1500V,5A,50W	23a$	Matsushita	BU208A,BU706,2SC2928,2SD954..
2SD59	Si-NPN	AF,Sw-Pow,100V,6A,50W	23a$	Mit	BD245C,BDV95,BDX95,2N5632..33..
2SD590	Si-NPN	AF,Sw,100V,2A,1W,<150/2100nS	2a$	Fui	2SD854,(BD379,BD529,2SD1177..78,..)
2SD591	Si-NPN	GenP,LN,30V,0,05A,0,15W,150MHz	7c	Mat	BC169,BC184,BC239,BC549,2SC2390+
2SD592(NC)	Si-NPN	GenP,30V,1A,0,75W,200MHz	7c	Mat	BC337..338,BC635,BC637,2SD1225..
2SD592A(ANC)	Si-NPN	=2SD592:60V	7c	-	BC637,BC639,2SD667,2SD1616..
2SD593	Si-NPN	Sw,500/400V,0,3A,0,8W,15MHz	2a$	Sak	2N5010..5015,2SC1762
2SD594	Si-NPN	=2SD593:800/700V	2a$	Sak	2N5013..5015
2SD595	Si-NPN	-		Nec	-
2SD596	Si-NPN	AF,30V,0,7A,170MHz	35a	NEC	BCW65..66,2SD1782
2SD596-DV1	Si-NPN	-	35	Nec	→2SD596
2SD596-DV2	Si-NPN	-	35	Nec	→2SD596
2SD596-DV3	Si-NPN	-	35	Nec	→2SD596
2SD596-DV4	Si-NPN	-	35	Nec	→2SD596
2SD596-DV5	Si-NPN	-	35	Nec	→2SD596
2SD596-V1	Si-NPN	-	35	Nec	→2SD596
2SD596-V2	Si-NPN	-	35	Nec	→2SD596
2SD596-V3	Si-NPN	-	35	Nec	→2SD596
2SD597	Si-NPN	AF,Sw-Pow,100V,5A,60W,7MHz	23a$	Mat	BD245C,BDV95,BDX95,2SD731..732..
2SD598	Si-NPN	=2SD597:120V,6A,80W,6MHz	23a$	Mat	BD245C,2SC2681,2SC4466,2SD731..732..
2SD599	Si-NPN	GenP,25V,1A,0,35W,180MHz	7c	Sanyo	BC337..338,BC635,BC637,2SD1225..
2SD60	Si-NPN	=2SD59:150/75V	23a$	Mit	BD245D,BDX11,2N3442,2SD551,2SD732,..
2SD600	Si-NPN	AF,Sw-Pow,Lo-sat,100V,1A,8W,130MHz	14h$	Sanyo	BD139,BD230,BD379,2SD1684..
2SD600K	Si-NPN	=2SD600:120V	14h$	-	2SC2690(A),2SD1382,2SD1563,2SD1684
2SD601	Si-NPN	GenP,30V,0,1A,150MHz	35a	Matsushita	BC846..848,BCW31..33,BCW71..72..
2SD601A	Si-NPN	-	35	Mat	→2SD601A
2SD601A-Q	Si-NPN	-	35	Mat	→2SD601A
2SD601A-R	Si-NPN	-	35	Mat	→2SD601A
2SD601A-S	Si-NPN	-	35	Mat	→2SD601A
2SD601-Q	Si-NPN	-	35	Mat	→2SD601
2SD601-R	Si-NPN	-	35	Mat	→2SD601
2SD601-S	Si-NPN	-	35	Mat	→2SD601
2SD602	Si-NPN	GenP,30V,0,5A,200MHz	35a	Matsushita	BC817..818,BCW65..66,BCX19..20..
2SD602A	Si-NPN	-	35	Mat	→2SD602A
2SD602A-Q	Si-NPN	-	35	Mat	→2SD602A
2SD602A-R	Si-NPN	-	35	Mat	→2SD602A
2SD602A-S	Si-NPN	-	35	Mat	→2SD602A
2SD602-Q	Si-NPN	-	35	Mat	→2SD602
2SD602-R	Si-NPN	-	35	Mat	→2SD602
2SD602-S	Si-NPN	-	35	Mat	→2SD602
2SD603	Si-NPN	GenP,30V,0,1A,0,25W,150MHz	9c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SD604	Si-NPN-Darl	AF,Sw-Pow,180/180V,5A,100W,B>400	23a$	Hit	2SD920..921,2SD1090,2SD1122..1123..
2SD605(D)	Si-NPN-Darl	Sw;Pow,600/500(D=-/280)V,7A,80W,B>200	23a$	Sak	BUW81(A),2SD520..521,2SD528,2SD705..
2SD606	Si-NPN-Darl	Sw,Pow,600/500V,15A,100W,B>200	23a$	Sak	BUT51P,2SD573,2SD683,2SD711A
2SD607	Si-NPN	-		Nec	-
2SD608	Si-NPN	AF,Sw-Pow,160/160V,1,5A,20W,45MHz	17j$	Nec	BD239D,2SC2592,2SC3364,2SD1562A..
2SD608A	Si-NPN	=2SD608:180/180V	17j$	-	BD239E,2SC2344,2SD608A
2SD609	Si-NPN	-		Nec	-
2SD61	Ge-NPN	AF,Sw,30V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD610	Si-NPN	AF,Sw-Pow,250/200V,2A,25W,5MHz	17j$	Nec	2SC2023,2SD772B
2SD611	Si-NPN	AF,Sw-Pow,100V,7A,30W	22a$	Fui	BD243C,BD543C,BD801,2N5429..30..
2SD611A	Si-NPN	=2SD611:120V	22a$	-	BD243C,BD543D,2SD550,2SD866
2SD612	Si-NPN	AF,Sw-Pow,25V,2A,10W,100MHz	14h$	Sanyo	BD329,BD375,2SD1380,2SD1506
2SD612K	Si-NPN	=2SD612:35V	14h$	-	BD375,2SD794(A),2SD1380,2SD1506
2SD613	Si-NPN	AF,Sw-Pow,100V,6A,40W,15MHz	17j$	Sanyo	BD243C,BD543C,BD801,2SD866..
2SD613P	Si-NPN	=2SD613:50W	19j$	-	2SD587..588,2SD883(A),2SD848(A)
2SD614	Si-NPN-Darl	AF,Sw,100/80V,3A,0,8W,B=3000	2a$	Sak	2SC2208,(BD681,BDW53C,D,2SD1091,..)
2SD615	Si-NPN-Darl	=2SD614:140/120V	2a$	Sak	(2SD830,2SD1091,2SD1128,2SD1169)

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2SD616	Si-NPN	AF,Sw-Pow,120V,7A,60W,15MHz	23a$	Sanyo	BD245C,2SC2681,2SD731..733,2SD1046..
2SD617	Si-NPN-Darl	AF,Sw-Pow,120/100V,8A,100W,B=2500	23a$	Sak	BDV65C,BDX63C,2SD922
2SD618	Si-NPN	-		Fui	-
2SD619	Si-NPN	GenP,80V,1,5A,0,5W,100MHz	7c	Fui	MPS651,2SC3328,2SD1665,2SD1857..
2SD62	Ge-NPN	AF,Sw,30V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD620	Si-NPN	=2SD619:	14h$	Fui	BD139,BD230,BD379,2SD1177..78..
2SD621	Si-NPN	TV-HD,2500/900V,3A,50W	23a$	Sanyo	2SD838
2SD622	Si-NPN	Sw,Pow,450/400V,3A,30W,25MHz	22a$	Fui	BUY63..65,TIP75B,C,2SC1466,2SC2929,..
2SD623	Si-NPN	-		Mit	-
2SD624	Si-NPN	Vid,200/150V,0,5A,0,8W,50MHz	2a$	Fui	2SD413,2SD576,(BF757..759,MPSU10..)
2SD625	Si-NPN	AF,Sw,250V,4A,6,2W(Tc=25°),60MHz	2a$	Son	BUY49,(BU406..409,2SC2767..)
2SD626	Si-NPN-Darl	Sw,Pow,600V,6A,80W,B>300,<1/45µS	23a$	Sanyo	BUW81,2SD520,2SD528,2SD605,2SD705..
2SD627	Si-NPN	TV-HD,1500/600V,3A,50W	23a$	Sanyo	BU208..209(A),BU706,2SC3023..24..
2SD628(H)	Si-N-Darl+Di	AF,Sw-Pow,,100V,10A,80W,B>1000	23a$	Hit	BDV65B,BDX83C,BDX85C,2N6059..
2SD629(H)	Si-N-Darl+Di	=2SD628:100W	23a$	Hit	BDV65B,BDX83C,BDX85C,2N6059..
2SD63	Ge-NPN	AF,Sw,25V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD630	Si-NPN	Sw,Pow,50V,30A,200W,0,8MHz	23a$	Fui	BDX41,BDY29,MJ802,2N3771
2SD631	Si-NPN	Sw,Pow,60V,40A,200W	23a$	Fui	2N6032,2N6274..6275
2SD632	Si-NPN	Sw,Pow,350/300V,2,5A,80W	23a$	Matsushita	BUX16B,C,TIP51..54,2SC1463,2SC2624
2SD633	Si-N-Darl+Di	AF,Sw-Pow,100V,7A,40W,B>2000	17j$	Tos	BD649,BD901,BDW73C,BDX53C..
2SD634	Si-N-Darl+Di	=2SD633:80V	17j$	Tos	BD647,BD899,BDW73B,BDX53B..
2SD635	Si-N-Darl+Di	=2SD633:60V	17j$	Tos	BD645,BD897,BDW73A,BDX53A..
2SD636	Si-NPN	GenP,30V,0,1A,0,4W,150MHz	9c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SD637	Si-NPN	=2SD636:60V	9c	Mat	BC174,BC182,BC190,BC546,2SD767..
2SD638	Si-NPN	GenP,30V,0,5A,0,6W,200MHz	9c	Mat	BC337..338,BC635,BC637,2SD1578..
2SD639	Si-NPN	=2SD638:60V	9c	Mat	BC637,BC639,2N3700..01,2SC2235..
2SD64	Ge-NPN	AF,Sw,25V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD640	Si-NPN	Sw,Pow,600/400V,7A,100W,3MHz	23a$	Tos	BU526,BU536,BU626A,2SD1094..
2SD641	Si-NPN	Sw,Pow,600/400V,15A,150W,4MHz	23a$	Tos	BUS13(A),BUW45..46,BUX48A..C
2SD642	Si-NPN	Sw,Pow,600/400V,40A,300W	68a$	Tos	2SC1435
2SD643	Si-NPN-Darl	Sw,Pow,300/200V,30A,300W,B>150	68a$	Tos	-
2SD644	Si-NPN-Darl	Sw,Pow,600/450V,30A,300W,B>150	68a$	Tos	-
2SD645	Si-NPN-Darl	Sw,Pow,600/450V,30A,350W,B>150	?74	Tos	-
2SD646(A)	Si-NPN-Darl	Sw,Pow,600/450V,50A,400W,B>150	?74	Tos	-
2SD647(A)	Si-NPN-Darl	Sw,Pow,800/600V,100A,770W,B>100	-	Tos	-
2SD648(A)	Si-NPN-Darl	Sw,Pow,300/300V,400A,2500W,B>100	-	Tos	-
2SD649	Si-NPN	TV-HD,1500/600V,6A,80W	23a$	Mat,Tos	BU2508A,2SC3025..26,2SC3685,2SD821..
2SD65	Ge-NPN	AF,Sw,25V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD650(H)	Si-N-Darl+Di	Sw,Pow,400/400V,6A,80W,B>500	23a$	Hitachi	BU180A,BU284,BU826
2SD651(H)	Si-NPN-Darl	Sw,Pow,400/400V,4A,30W,B>500	22a$	Hit	BU910..912,2SD977,2SD1072,2SD1245,..
2SD652	Si-NPN-Darl	Sw,Pow,500/500V,6A,80W,B=3000	23a$	Hit	BU322(A),BUW81,2SD796,2SD980..
2SD654	Si-NPN	GenP,50V,0,5A,0,57W,190MHz	2a$	Mit	BC140..141,BC300..302,2N3053..
2SD655	Si-NPN	GenP,30V,0,7A,0,5W,250MHz	7c	Hit	BC337..338,BC635,BC637,2SD1578..
2SD656	Si-NPN	Sw,Pow,200/180V,1,5A,30W,>2MHz	22a$	Tos	BD239F,BUX67(A..C),2SC783,2SD1138,..
2SD657	Si-NPN	Sw,Pow,200/200V,1,5A,50W	23a$	Toshiba	BD239F,2SC1195,2SC2809,2SD632
2SD658	Si-NPN	TV-HD,1500/600V,5A,50W	23a$	Hitachi	BU208A,BU706,2SC2928,2SD820..
2SD659	Si-NPN	-		Fui	-
2SD66	Ge-NPN	AF,Sw,25V,0,1A,0,12W	2a	Son	AC127,2SD30
2SD660	Si-NPN	GenP,Sw,90V,2A,1W,150/2100nS	2a$	Fui	BCX40,BSS15,BSV84,2N5320..
2SD661	Si-NPN	GenP,LN,35V,0,1A,0,4W,200MHz	9c	Mat	BC169,BC184,BC239,BC549,2SC2240+
2SD661A	Si-NPN	=2SD661:55V	9c	-	BC414,BC550,2SC2675,2SC2390..
2SD662	SI-NPN	Vid,250/200V,0,07A,0,6W,80MHz	9c	Mat	BF298..299,BF422A,2SC3468,2SC4218..
2SD662B	Si-NPN	=2SD662:400/400V	9c	-	2SC2267,2SC3469,2SC4166,2SD1385
2SD663	Si-N-Darl+Di	Sw,Pow,500/500V,6A,80W,B>400	23a$	Fjd	BUW81,2SD520,2SD528,2SD605,2SD705..
2SD664	Si-N-Darl+Di	AF,Sw-Pow,80V,7A,40W,B>2000	22a$	Tos	BD647,BD899,BDW73B,BDX53B..
2SD665	Si-NPN	Sw,Pow,200/200V,15A,150W,15MHz	23a$	Toshiba	BDW16,2SC2607..2608,2SD552,2SD583,..
2SD666(A)	Si-NPN	GenP,120V,0,05A,0,9W,140MHz	7c(9mm)	Hit	2SC2632,2SC3245(A),2SC3248,2SC3800
2SD667(A)	Si-NPN	=2SD666(A):1A	7c(9mm)	Hit	2SC2383,2SC3228,2SD1292,2SD1812
2SD668(A)	Si-NPN	AF,Sw-Vid-Pow,180V,0,05A,20W,140MHz	14h$	Hit	BF469,BF471,BF415,BF417,2SC3416
2SD669(A)	Si-NPN	=2SD668:1,5A	14h$	Hit	2SC3117
2SD67	Si-NPN	Sw,Pow,120V,5A,50W,100MHz	23a$	Sanyo	2SC2706,2SC2837,2SC2987(A),2SD1047
2SD670(H)	Si-N-Darl+Di	AF,Sw-Pow,100V,15A,100W,B>1000	23a$	Hit	BDV67A,BDW83C,BDX67B,MJ4035..
2SD671	Si-NPN	GenP,30V,0,5A,0,6W,150MHz	7c	Mat	BC337..338,BC635,BC637,2SC3377..
2SD672	SI-NPN	Sw,Pow,300V,1A,40W(Tc=45°),20MHz	23a$	Matsushita	2SC1463,2SC2809,2SD632

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2SD673(A)	Si-NPN	AF,Sw-Pow,120V,7A,60W,8MHz	23a$	Hit	BD245C,2SC2681,2SC4466,2SD731..733..
2SD674(A)	Si-NPN	=2SD673:80W	23a$	Hit	BD245C,2SC2681,2SC4466,2SD731..733..
2SD675(A)	Si-NPN	AF,Sw-Pow,160V,12A,100W,8MHz	23a$	Hit	BD745F,2SD424,2SD733,2SD1047..
2SD676(A)	Si-NPN	=2SD675:125W	23a$	Hit	BD745F,2SC2607..2608,2SD753..
2SD677	Si-NPN	Sw,Pow,450V,5A,100W	23a$	Fujitsu	BU426(A),BUW11(A),BUW71,BUX45..
2SD678	Si-NPN-Darl	AF,Sw-Pow,60V,3A,25W,B>1000	17j$	Mat	BD715,BDW23A,BDW53A,2SD837..
2SD678A	Si-NPN-Darl	=2SD678:80V	17j$	-	BD717,BDW23B,BDW53B,2SD837A..
2SD679	Si-NPN-Darl	AF,Sw-Pow,70V,4A,40W,B>1000	17j$	Mat	BD717,BDW23B,BDW53B,BDW63B..
2SD679A	Si-NPN-Darl	=2SD679:90V	17j$	-	BD901,BDW23C,BDW53C,BDW63C..
2SD68	Si-NPN	=2SD67:75V	23a$	Sanyo	2SC2681,2SC2706,2SC2837,(BD245B,..)
2SD680	Si-NPN-Darl	AF,Sw-Pow,90V,6A,60W,B>1000	23a$	Mat	BDV65B,BDX63B,TIP142,2SD1170..
2SD680A	Si-NPN-Darl	=2SD680:110V	23a$	-	BDV65C,BDX63C,TIP142,2SD1170..
2SD681	Si-NPN-Darl	AF,Sw-Pow,100V,8A,80W,B>1000	23a$	Mat	BDV65B,BDX63B,BDX83C,TIP142..
2SD681A	Si-NPN-Darl	=2SD681:120V	23a$	-	BDV65C,BDW84D,BDX63C,BDX65C..
2SD682	Si-NPN-Darl	AF,Sw-Pow,120V,8A,110W,B>1000	23a$	Mat	BDV65C,BDV67B,BDW83D,BDX65C..
2SD682A	Si-NPN-Darl	=2SD682:140V	23a$	-	BDV67C,2SD1296,2SD1299
2SD683	Si-N-Darl+Di	Sw,Pow,600/400V,15A,150W,B>500	23a$	Tos	BUT51,2SD573,2SD606,2SD711A
2SD683A	Si-N-Darl+Di	=2SD683:600/450V	23a$	-	BUT51,2SD573,2SD606,2SD711A
2SD684	Si-NPN-Darl	Sw,Pow,600/300V,6A,30W,B>1500	22a$	Tos	BU810,2SC3579,2SD798..799
2SD684A	Si-N-Darl+Di	Sw,Pow,600/400V,6A,30W,B>600	22a$	-	BU810,2SC3579,2SD799
2SD685	Si-N-Darl+Di	Sw,Pow,600/400V,10A,100W,B>400	23a$	Tos	BUW81(A),MJ10013..14,2SC3262
2SD686	Si-N-Darl+Di	AF,Sw-Pow,100V,4A,30W,B>2000	17j$	Tos	BD901,BDW23C,BDW53C,BDW63C..
2SD687	Si-N-Darl+Di	AF,Sw-Pow,60V,3A,25W,B>2000	17j$	Tos	BD899,BDW23A,BDW53A,BDW63A..
2SD688	Si-NPN-Darl	AF,Sw,100V,1,5A,8W(Tc=25°),B>2000	2a$	Tos	2SC1879,2SD406,(BD681)
2SD689	Si-NPN-Darl	=2SD688:10W	17j$	Tos	BDT61B,BDW53C,2SD837B
2SD69	Si-NPN	AF,Sw-Pow,140V,3A,50W,13MHz	23a$	Son	BDX12,2N5760,2SC2706,2SC2837..
2SD690	Si-NPN	AF,Sw-Pow,70V,7A,40W,10MHz	22a$	Tos	BD543B,BD799,BD809,2N6372..73..
2SD691	Si-N-Darl+Di	AF,Sw-Pow,100V,6A,40W,B>500	22a$	Mat	BD649,BD901,BDW73C,BDX53C..
2SD692	Si-N-Darl+Di	=2SD691:50W	23a$	Mat	BDV65B,BDX63B,BDX83C,BDX85C..
2SD693	Si-N-Darl+Di	Sw,Pow,450/450V,10A,80W,B>150	23a$	Matsushita	BU922,BUW81(A),MJ10003,2SD685..
2SD694	Si-NPN-Darl	Sw,Pow,400/350V,30A,300W,B>150	68a$	Tos	-
2SD695	Si-NPN-Darl	Sw,Pow,400/350V,30A,350W,B>150	?74	Tos	-
2SD696(A)	Si-NPN-Darl	Sw,Pow,400/350V,50A,400W,B>150	?74	Tos	-
2SD697(A)	Si-NPN-Darl	Sw,Pow,500/450V,100A,770W,B>100	-	Tos	-
2SD698	Si-NPN-Darl	Sw,Pow,200/200V,600A,2500W,B>150	-	Tos	-
2SD699	Si-NPN-Darl	Sw,Pow,300/200V,30A,250W,B>150	68a$	Tos	-
2SD70	Si-NPN	AF,Sw-Pow,40V,2A,15W	22a$	Nec	BD239,BD241,BD933,2SC2528..
2SD700(D)	Si-NPN-Darl	Sw,Pow,300/200V,200A,770W,B>150	-	Tos	-
2SD701	Si-NPN	-		Tos	-
2SD702	Si-NPN	Sw,Pow,400/300V,40A,300W	68a$	Tos	2SC1435,2SC2366,2SD642
2SD703	Si-NPN-Darl	Sw,Pow,200/150V,30A,300W,B>150	68a$	Tos	-
2SD704	Si-NPN	AF,Sw-Pow,50V,5A,40W,10MHz	18j$	Mit	BD245(A..C),BDV91,BDV93,BDV95..
2SD705	Si-NPN-Darl	Sw,Pow,600V,8A,80W,B=300	23a$	Fujitsu	BUW81(A),2SD520,2SD528,2SD605..
2SD706	Si-NPN-Darl	Sw,Pow,345V,6A,80W,B=1000	23a$	Fujitsu	BU322(A),BUX28..29,2SD720..
2SD707	Si-N-Darl+Di	Sw,Pow,500V,8A,100W,B>200	23a$	Fjd	BU922,BUW81(A),MJ10013..14..
2SD708	Si-NPN-Darl	Sw,Pow,345V,6A,30W,B=1000	22a$	Fjd	BU910..912,2SD835,2SD1114,2SD1245,..
2SD709	Si-NPN-Darl	Sw,Pow,250V,4A,25W,B>1500	22a$	Fjd	2SD816,2SD834,2SD1073
2SD71	Si-NPN	AF,Sw-Pow,100V,2A,15W	22a$	Nec	BD239C,BD241C,BD937,2SC2528..
2SD710	Si-NPN-Darl	Sw,Pow,300V,15A,150W,B=500	23a$	Fujitsu	BU930..932,2SD572..573,2SD683..
2SD711	Si-NPN-Darl	Sw,Pow,500/450V,15A,100W,B>100	23a$	Fjd	BU932,2SD572..573,2SD606,2SD683..
2SD711A	Si-NPN-Darl	=2SD711:600/600V,B>200	23a$	-	BUT51P,2SD573,2SD606,2SD683..
2SD712	Si-NPN	AF,Sw-Pow,100V,4A,30W,8MHz	17j$	Mit	BD243C,BD539C,BD953,2SD613..
2SD712A	Si-NPN	=2SD712:280V	17j$	-	TIP75(A..C),2SC2826,2SC2929..
2SD713	Si-NPN	AF,Sw-Pow,100V,5A,40W,8MHz	17j$	Mit	BD243C,BD539C,BD953,2SD613..
2SD714	Si-NPN	-		Mit	-
2SD715	Si-NPN-Darl	AF,Sw-Pow,110V,7A,80W,B>2000	18j$	Mit	BDV65C,BDW83D,2SD1210
2SD716	Si-NPN	AF-Out,100V,6A,60W,12MHz	18j$	Tos	BD245C,BDV95,2SC2681,2SD895..96..
2SD717	Si-NPN	Lo-sat,70V,10A,80W,10MHz	18j$	Tos	2SD1187,2SD1238L
2SD718	Si-NPN	AF,Sw-Pow,120V,8A,80W,12MHz	18j$	Tos	BD245C,2SC2681,2SC2706,2SC2837..
2SD72	Ge-NPN	AF,25V,0,6A,0,21W	2a	Sanyo	AC176,AC187,2SD352
2SD720	Si-NPN-Darl	Sw,Pow,400/400V,7A,100W,B>400	23a$	Mitsubishi	BU322(A),BUX29,2SD707,2SD796..
2SD721	Si-NPN-Darl	AF,Sw-Pow,100V,6A,50W,B=1000	17j$	Sak	BD649,BD901,BDW73C,BDX53C..
2SD722	Si-NPN-Darl	=2SD721:120V	17j$	Sak	BD651,BDT21,BDW73D,BDX53E..
2SD723	Si-NPN	AF,Sw-Pow,100V,4A,40W	17j$	Hit	BD243C,BD539C,BD953,2SD712..

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2SD724	Si-NPN	AF,Sw-Pow,200V,4A,30W	17j$	Hit	BD243F,2SC2767,2SD772A,B
2SD725	Si-NPN	TV-HD,1500/600V,6A,50W	23a$	Hitachi	2SC2027
2SD726	Si-NPN	AF,Sw-Pow,100V,4A,40W,10MHz	17j$	Hit	BD243C,BD539C,BD953,2SD712..
2SD727	Si-NPN	AF,Sw-Pow,130V,5A,60W,7MHz	18j$	Mat	BD245D,2SD731,2SD751,2SD1046..
2SD728	Si-NPN	=2SD727:150V,6A,70W	18j$	Mat	BD245D,2SC3263,2SD731,2SD751..
2SD729(H)	Si-N-Darl+Di	AF,Sw-Pow,100V,20A,125W,B>1000	23a$	Hit	BDX69B,MJ11014,2N6284,2SD1460
2SD72K	Ge-NPN	=2SD72:0,72W	3a	-	AC176K,AC187K,2SD352
2SD73	Si-NPN	AF,Sw-Pow,100V,5A,60W,20MHz	23a$	Nec	BD245C,BDV95,BDX95,2N5632..33..
2SD730(H)	Si-N-Darl+Di	=2SD729:25A	23a$	Hit	BDX69B,MJ11014,MJ11016,2SD1460
2SD731	Si-NPN	AF,Sw-Pow,170V,7A,80W,7MHz	18j$	Mat	BD245E,2SC3263,2SD751
2SD732(K)	Si-NPN	AF,Sw-Pow,150V,8A,80W,15MHz	23a$	Sanyo	BD245D,2SC2837,2SD551,2SD752..
2SD733	Si-NPN	AF,Sw-Pow,160/140V,12A,100W,15MHz	23a$	Sanyo	BD745E,MJ15015,2SC2607..08..
2SD733K	Si-NPN	=2SD733:180/160V	23a$	-	BD757F,MJ15015,2SC2607..08..
2SD734	Si-NPN	GenP,Lo-sat,25V,0,7A,0,6W,250MHz	7c	Sanyo	2SC4483,2SD1207,2SD1302,2SD1616..
2SD735	Si-NPN	AF,Sw-Pow,160/120V,12A,100W	20j$	Hit	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SD736(A)	Si-NPN	=2SD735:160/140V	20j$	Hit	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SD737	Si-NPN	AF,Sw-Pow,160V,12A,120W	20j$	Hit	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SD738(A)	Si-NPN	AF,Sw-Pow,160V,12A,125W	20j$	Hit	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SD74	Si-NPN	=2SD73:150/90V	23a$	Nec	BD245D,BDX11,2N3442,2SD551,2SD732
2SD741	Si-NPN	HF/AF,Sw-Pow,40V,5A,15W,200MHz	14h$	Nec	MJE200,2SC2270,2SC2594
2SD742	Si-NPN	-		Nec	-
2SD743(A)	Si-NPN	AF,Sw-Pow,100V,4A,40W,17MHz	17j$	Nec	BD243C,BD539C,BD953,2SD726..
2SD744	Si-NPN	-		Nec	-
2SD745	Si-NPN	AF,Sw-Pow,140/140V,10A,120W,15MHz	20j$	Nec	2SC2564..2565,2SC2838,2SD845..
2SD745A	Si-NPN	=2SD745:150/150V	20j$	-	2SC2526,2SC2565,2SC2838,2SD845..
2SD745B	Si-NPN	=2SD745:160/160V	20j$	-	2SC2526,2SC2565,2SC2766(A),2SC2921,..
2SD746	Si-NPN	AF,Sw-Pow,180V,10A,200W,15MHz	4-SILP	Nec	-
2SD746A	Si-NPN	=2SD746:220V	4-SILP	-	-
2SD747	Si-NPN	Sw,50V,0,5A,<1µS	2a$	Mit	BSW61..64,BSX33,2N2221..2222(A)..
2SD748	Si-NPN	Sw,Pow,250/200V,3A,80W	23a$	Hitachi	TIP51..54,2SC1463,2SD632,2SD1018
2SD748A	Si-NPN	=2SD748:250/250V	23a$	-	TIP51..54,2SC1463,2SD632,2SD1018
2SD749	Si-NPN	Sw,Pow,750/300V,3A,50W	23a$	Mat	BUW11(A),BUX46(A),2SC3088,2SC3448..
2SD75(H)	Ge-NPN	AF,25V,0,1A,0,15W	2a	Hit	AC127,AC176,AC187,2SD30
2SD750	Si-NPN	AF,Sw-Pow,110/80V,15A,100W,1MHz	23a$	Mat	BD317,BD745C,2N3055,2N5629..31..
2SD751	Si-NPN	AF,Sw-Pow,200/140V,9A,100W,7MHz	18j$	Mat	BD245F,2SC3263,2SC3855
2SD752	Si-NPN	AF,Sw-Pow,160/160V,15A,150W	23a$	Hit	BDW12,MJ15015,2N3773,2SC2607..08,..
2SD753	Si-NPN	=2SD752:200/200V	23a$	Hit	BDW16,MJ15015,2SC1585,2SC2607..08..
2SD754	Si-NPN	GenP,25V,0,7A,0,625W,280MHz	7e	Hit	(BC337..338,BC635,BC637,2SD1225..)
2SD755	Si-NPN	GenP,100V,0,05A,0,75W,350MHz	7c(9mm)	Hit	2SC2632,2SC3245(A),2SC3248,2SD3800
2SD756	Si-NPN	=2SD755:120V	7c(9mm)	Hit	2SC2632,2SC3245(A),2SC3248,2SC3800
2SD756A	Si-NPN	=2SD755:140V	7c(9mm)	-	2SC2375,2SC2631..32,2SC3248,2SC3245A,..
2SD757	Si-NPN	AF,Sw-Vid-Pow,160/160V,0,05A,140MHz	17j$	Hit	2SC3514,(BF415,BF417,BF469,BF471,..)
2SD758	Si-NPN	=2SD757:200/200V	17j$	Hit	2SC1819,(BF415,BF417,BF469,BF471,..)
2SD759	Si-NPN	AF,Sw-Pow,160/160V,2A,25W,100MHz	17j$	Hit	2SC2529,2SC2660
2SD75A(AH)	Ge-NPN	=2SD75:45V	2a	-	-
2SD760	Si-NPN	=2SD759:200/200V	17j$	Hit	2SC2660,2SD772A..B
2SD761	Si-NPN	AF,Sw-Pow,180/180V,1,5A,20W	17j$	Sanyo	BD239E,2SD608A,2SD610,2SD1138..
2SD762	Si-NPN	AF,Sw-Pow,60V,3A,25W	17j$	Mat	BD241A,BD535,BD935,2SC3179..
2SD762A	Si-NPN	=2SD762:80V,4A,30W	17j$	-	BD243B,BD537,BD951,2SC3179..
2SD763	Si-NPN	GenP,TV-HD,120V,1A,0,9W	7c(9mm)	Hit	(2SC2383,2SC3228,2SD667(A),2SD1812)
2SD764	Si-NPN	TV-HD,1500/600V,1,5A,50W	23a$	Hitachi	BU205..206,2SD1492,2SC1922,2SD818..
2SD765	Si-NPN	TV-HD,1500/800V,3A,50W	23a$	Hitachi	BU207..209A,BU706,2SC3023..24..
2SD766	Si-NPN	Sw,Pow,AF-Pow,300V,0,7A,30W,45MHz	22a$	Mat	BUW40(A,B),TIP47..50,2SC782..
2SD767	Si-NPN	GenP,60V,0,1A,0,25W,150MHz	7c	Mat	BC174,BC182,BC190,BC546,2SC2240+
2SD768(K)	Si-N-Darl+Di	AF,Sw-Pow,120V,6A,40W,B>1000	17j$	Hit	BD651,BDW63D,BDW73D,BDT21..
2SD769	Si-NPN	GenP,20V,0,5A,0,4W	7c	Mat	BC337..338,BC635,BC637,2SC3377..
2SD77(H)	Ge-NPN	AF,25V,0,1A,0,15W	2a	Hit	AC127,AC176,AC187,2SD30
2SD770	Si-NPN	=2SD769:50V	7c	Mat	BC337,BC635,BC637,2SD1226..
2SD771	Si-NPN	GenP,25V,0,05A,0,15W	7c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SD772	Si-NPN	AF,Sw-Pow,150/80V,5A,40W,40MHz	17j$	Mat	MJE15030,2SC4328
2SD772A	Si-NPN	=2SD772:200/80V	17j$	-	2SC2767
2SD772B	Si-NPN	=2SD772:250/80V	17j$	-	2SC2767
2SD773	Si-NPN	AF,Lo-sat,20V,2A,1W,110MHz	9b	NEC	2SC3225,2SC4484,2SD1246..47
2SD774	Si-NPN	GenP,100V,1A,1W,95MHz	9b	NEC	2SD1616A,2SD1665,2SD1768,2SD1857..

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2SD775	Si-NPN	-		Nec	-
2SD776	Si-NPN	Sw,Pow,Hi-beta,200V,5A,100W,B>500	23a$	Tos	2SD1090
2SD777	Si-NPN	TV,Reg,Hi-beta,55V,4A,100W,B>500	23a$	Toshiba	-
2SD778	Si-NPN	GenP,30V,0,1A,0,4W	9c	Mat	BC168,BC183,BC238,BC548,2SD767..
2SD779	Si-NPN	=2SD778:60V	9c	Mat	BC174,BC182,BC190,BC546,2SD767..
2SD77A(AH)	Ge-NPN	=2SD77:45V	2a	-	-
2SD78(A)(M)	Si-NPN	AF,Sw,100/60(A=100/80)V,2A,1W	2a$	Nec	BCX40,BSS15,2N5320,(BD529,..)
2SD780	Si-NPN	GenP,60V,0,3A,140MHz	35a	NEC	BCW65..66,2SD1782
2SD780A	Si-NPN	=2SD780:80V	35a	-	BCW66,2SD1782
2SD780A-D51	Si-NPN	-	35	Nec	→2SD780A
2SD780A-D52	Si-NPN	-	35	Nec	→2SD780A
2SD780A-D53	Si-NPN	-	35	Nec	→2SD780A
2SD780A-D54	Si-NPN	-	35	Nec	→2SD780A
2SD780A-D55	Si-NPN	-	35	Nec	→2SD780A
2SD780-DW1	Si-NPN	-	35	Nec	→2SD780
2SD780-DW2	Si-NPN	-	35	Nec	→2SD780
2SD780-DW3	Si-NPN	-	35	Nec	→2SD780
2SD780-DW4	Si-NPN	-	35	Nec	→2SD780
2SD780-DW5	Si-NPN	-	35	Nec	→2SD780
2SD780-V4	Si-NPN	-	35	Nec	→2SD780
2SD780-V5	Si-NPN	-	35	Nec	→2SD780
2SD780-V6	Si-NPN	-	35	Nec	→2SD780
2SD781	Si-NPN	Sw,Pow,TV-HD,150/60V,2A	14h$	Hit	2SD975
2SD782	Si-NPN	TV-HD,300/80V,5A,30W	17j$	Hit	BU406..408,2SD884..885,2SD1150..
2SD783	Si-NPN	TV-HD,1500/600V,4A,50W	23a$	Hitachi	BU208A,BU706,2SC2928,2SD1495..
2SD784	Si-NPN	=2SD783:1700/700V,5A	23a$	Hit	BU209(A),2SC3026,2SD1434
2SD785	Si-NPN	=2SD783:1900/700V,5A	23a$	Hit	2SC2125
2SD786(S)	Si-NPN	AF,LN,50V,0,3A,0,25W,100MHz	7c,41c	Rhm	BC414,BC550,2SC2390,2SC2674..75..
2SD787	Si-NPN	AF-Pow,20/16V,2A,0,9W,100MHz	7c(9mm)	Hit	2SD1100,2SD1014,2SD1146,2SD1207..
2SD788	Si-NPN	=2SD787:20/20V	7c(9mm)	Hit	2SD1100,2SD1014,2SD1146,2SD1207..
2SD789	Si-NPN	AF-Pow,100/50V,1A,0,9W,100MHz	7c(9mm)	Hit	2SC2383,2SC3228,2SD667(A),2SD1812..
2SD79	Si-NPN	=2SD78:	43a$	Nec	(BD237,BD239C,BD529,BD817,..)
2SD790	Si-NPN	=2SD789:100/70V	7c(9mm)	Hit	2SC2383,2SC3228,2SD667(A),2SD1812..
2SD791	Si-NPN	-		Son	-
2SD792	Si-NPN	TV-HD,1500/700V,5A,35W(Tc=90°)	23a$	Matsushita	BU208A,BU706,2SC2928,2SD954..
2SD793	Si-NPN	AF,Sw-Pow,40V,3A,10W,65MHz	14h$	Nec	BD785,MJE240..244,2SD1348
2SD794(A)	Si-NPN	AF,Sw-Pow,70V,3A,10W,60MHz	14h$	Nec	BD787,BD789,MJE240..244
2SD795(A)	Si-NPN	AF/HF-Pow,50V,3A,20W,95MHz	17j$	Nec	2SC3252
2SD796	Si-N-Darl+Di	Sw,Pow,500V,8A,100W,B>200,<1,4/21µS	23a$	Fjd	BU922,BUW81(A),2SD707,2SD685..
2SD797	Si-NPN	Sw,Pow,100V,30A,200W,3MHz,1,5/7µS	23a$	Toshiba	BDW30,BDY29,MJ802
2SD798	Si-NPN-Darl	Sw,Pow,600/300V,6A,30W,B>1500	17j$	Tos	BU810,2SC3579
2SD799	Si-N-Darl+Di	Sw,Pow,600/400V,6A,30W,B>600	17j$	Tos	BU810,2SC3579
2SD80	Si-NPN	AF,Sw-Pow,30V,6A,50W,1320/4500nS	23a$	Sak	BD245,BDV91,BDX91,2N5873..74..
2SD800	Si-NPN	Sw,Pow,750V,4A,30W,8MHz	23a$	Hit	BUS11(A),BUW11(A),BUX82..83..
2SD801	Si-NPN	Sw,Pow,TV-SN,800/375V,6A,50W	23a$	Hitachi	BU326(A),BU426(A),BUS26,2SD1093
2SD802	Si-NPN	=2SD801:900/400V	23a$	Hit	BU326A,BU426A,BUS26,2SD1093
2SD803	Si-N-Darl+Di	AF,Sw-Pow,120V,8A,100W,B>2000	23a$	Mat	BDV65C,BDX63C,2SD922,2SD1210..
2SD804	Si-NPN	AF,Sw-Pow,60V,3A,25W	17j$	Mat	BD241A,BD535,BD935,2SC3179..
2SD805	Si-NPN-Darl	Sw,Pow,600/600V,30A,200W,B>100	68a$	Fjd	-
2SD806	Si-NPN-Darl	=2SD805:50A,400W	?74	Fjd	-
2SD807	Si-NPN	TV-HD,1500/800V,5A,50W	23a$	Sanken	BU208A,BU706,2SC2928,2SD954..
2SD808	Si-NPN	GenP,25V,0,5A,0,4W,250MHz	7c	Hit	BC337..338,BC635,BC637,2SD1578..
2SD809(1)	Si-NPN	AF,Sw-Pow,Lo-sat,100V,1A,10W,85MHz	14h$	Nec	BD139,BD230,BD379,2SD1177..78..
2SD81	Si-NPN	=2SD80:60/40V	23a$	Sak	BD245A,BDV91,BDX91,2N5873..74..
2SD810	Si-NPN	Hi-beta,20/20/20V,4A,30W,B=400	17j$	Sak	-
2SD811	Si-NPN	Sw,Pow,900/400V,6A,50W,5MHz	23a$	Tos	BU526,BU536,BUW12A,BUX47A..
2SD812	Si-NPN	AF,Sw-Pow,80V,5A,40W,15MHz	17j$	Mat	BD243B,BD539B,BD951,2SD613..
2SD813	Si-NPN	Lo-sat,25V,0,5A,150MHz	35a	Mat	2SC3265,(BC817..818,BCX19..20)
2SD814	Si-NPN	LN,150/150V,0,05A,150MHz	35a	Mat	-
2SD814A	Si-NPN	-	35	Mat	→2SD814A
2SD814A-Q	Si-NPN	-	35	Mat	→2SD814A
2SD814A-R	Si-NPN	-	35	Mat	→2SD814A
2SD814A-S	Si-NPN	-	35	Mat	→2SD814A
2SD814A-T	Si-NPN	-	35	Mat	→2SD814A

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2SD814-Q	Si-NPN	-	35	Mat	→2SD814
2SD814-R	Si-NPN	-	35	Mat	→2SD814
2SD814-S	Si-NPN	-	35	Mat	→2SD814
2SD814-T	Si-NPN	-	35	Mat	→2SD814
2SD815	Si-NPN-Darl	Sw,Pow,120V,30A,300W,B=300,<3/11µS	68a$	Fjd	-
2SD816	Si-NPN-Darl	Sw,Pow,300V,4A,30W,B=1500,<2/20µS	17j$	Fjd	2SD1073
2SD817	Si-NPN	TV-HD,1500/600V,1,5A,50W	23a$	Toshiba	BU205,2SD1492,2SC1922,2SC3023..24..
2SD818	Si-NPN	TV-HD,1500/600V,2,5A,50W	23a$	Toshiba	BU205,BU505,BU705,2SC1922,2SD849..850..
2SD819	Si-NPN	=2SD818:3,5A	23a$	Tos,Tho	BU208A,BU706,BU4506AX,2SC3023..24,2SD1495,..
2SD82	Si-NPN	=2SD80:100/60V	23a$	Sak	BD245C,BDV93,BDX93,2N5632..33..
2SD820	Si-NPN	=2SD818:5A	23a$	Tos	BU208A,BU706,BU4507AX,2SC2928,2SD954,..
2SD821	Si-NPN	=2SD818:6A	23a$	Tos	BU2508A,BU4508AX,2SC3025..26,2SC3685,2SD649..
2SD822	Si-NPN	=2SD818:7A	23a$	Tos	BU2508A,2SC3027..28,2SD1016,2SC3686
2SD823	Si-NPN	AF,Sw-Pow,TV-HD,200/90V,6A,40W	17j$	Sanyo	BU406..409,2SD884..885,2SD1150..
2SD824(A)	Si-NPN	AF,Sw-Pow,120V,6A,60W,10MHz	20j$	Hit	2SC2525..26,2SC2564..65,2SD745(A,B),..
2SD825(A)	Si-NPN	AF,Sw-Pow,120V,7A,80W,10MHz	20j$	Hit	2SC2525..26,2SC2564..65,2SD745(A,B),..
2SD826	Si-NPN	Lo-sat,60V,5A,10W,120MHz	14h$	Sanyo	BDX35..37
2SD827	Si-N-Darl+Di	Sw,Pow,500/500V,4A,50W,B>500	20j$	Hit	(2SD932)
2SD828	Si-N-Darl+Di	=2SD827:B=2000	20j$	Hit	(2SD932)
2SD829(K)	Si-N-Darl+Di	AF,Sw-Pow,150/120V,15A,100W,B=4000	20j$	Hit	(2SD852)
2SD83	Si-NPN	=2SD80:150/75V	23a$	Sak	BD245D,BDX11,2N3442,2SD551,2SD732,..
2SD830	Si-NPN-Darl	AF,Sw-Pow,150/100V,5A,30W,B>2000	17j$	Fui	BDX53F,2SD1128,2SD1169,2SD1500
2SD831	Si-NPN-Darl	Sw,Pow,500/400V,20A,150W,B=500	23a$	Fujitsu	BUT13,MJ10001,MJ10005,MJ10008..09
2SD832	Si-NPN-Darl	Sw,Pow,600/400V,50A,400W,B=200	?74	Fui	-
2SD833	Si-N-Darl+Di	AF,Sw-Pow,60V,7A,40W,B>4000	17j$	Fjd	2SD2024
2SD834	Si-NPN-Darl	Sw,Pow,250/200V,4A,25W,B>1500	17j$	Fjd	2SD816,2SD1073
2SD835	Si-N-Darl+Di	Sw,Pow,400/400V,6A,40W,B>400	17j$	Fjd	BU910..912,2SD1114,2SD1245
2SD836	Si-N-Darl+Di	AF,Sw-Pow,60V,2A,35W,B>1000	17j$	Mat	BD715,BDT61,BDW53A,BDW63A..
2SD836A	Si-N-Darl+Di	=2SD836:80V	17j$	-	BD717,BDT61A,BDW53B,BDW63B..
2SD836B	Si-N-Darl+Di	=2SD836:100V	17j$	-	BDT61B,BDW53C,BDW63C..
2SD837	Si-N-Darl+Di	AF,Sw-Pow,60V,4A,40W,B>1000	17j$	Mat	BD645,BD897,BDW23A,BDW63A..
2SD837A	Si-N-Darl+Di	=2SD837:80V	17j$	-	BD647,BD899,BDW23B,BDW63B..
2SD837B	Si-N-Darl+Di	=2SD837:100V	17j$	-	BD649,BD901,BDW23C,BDW63C..
2SD838	Si-NPN	TV-HD,2500/900V,3A,50W	23a$	Sanyo	2SD621
2SD839	Si-NPN-Darl	AF,Sw-Pow,35V,4A,30W,B>1000	17j$	Mit	BD713,BDW23,BDW53,BDW63..
2SD84	Si-NPN	=2SD80:200/85V	23a$	Sak	BD245F,BD550A,B,2SC2262,2SD751
2SD840	Si-NPN-Darl	AF,Sw-Pow,70V,5A,40W,B>1000	17j$	Mit	BD647,BD899,BDW23B,BDW63B..
2SD841	Si-NPN	Sw,Pow,TV-SN,800/400V,3A,40W,4MHz	17j$	Tos	BUT11(A),BUV46(A),2SC3047,2SC3086..
2SD842	Si-N-Darl+Di	AF,Sw-Pow,80V,30A,150W,B=4000	23a$	Tos	BDX69A..C,MJ11014,2SD1460..
2SD843	Si-NPN	Lo-sat,100V,7A,40W,10MHz	17j$	Tos	2SD866
2SD844	Si-NPN	AF,Sw-Pow,Lo-sat,50V,7A,60W,15MHz	18j$	Tos	2SD1063
2SD845	Si-NPN	AF,Sw-Pow,150V,12A,120W,20MHz	20j$	Tos	2SC2526,2SC2766(A),2SC2838,2SC2921,..
2SD846	Si-NPN	AF,Sw-Pow,200V,15A,150W,20MHz	20j$	Tos	2SC2773..2774,2SC3264,2SC3370
2SD847	Si-NPN	AF,Sw-Pow,40V,15A,80W	18j$	Fjd	BD249,BD545,BD745,2SC3256,2SD1065
2SD848	Si-NPN	AF,Sw-Pow,120V,7A,80W	19j$	Nec	2SC2276,2SD588
2SD848A	Si-NPN	=2SD848:130V	19j$	-	2SC2276,2SD588
2SD849	Si-NPN	TV-HD,1500/600V,3A,70W	23a$	Matsushita	BU208A,BU706,2SD850,2SD1495..
2SD850	Si-NPN	TV-HD,1500/700V,3A,65W	23a$	Matsushita	BU208A,BU706,2SD849,2SD1495..
2SD851	Si-N-Darl+Di	Sw,Pow,150V,10A,80W,B=3000,1/7µS	20j$	Nec	2SD829,2SD2401
2SD852	Si-N-Darl+Di	Sw,Pow,150V,15A,100W,B=3000	20j$	Nec	2SD829
2SD853	Si-NPN	-		Nec	-
2SD854	Si-NPN	Sw,100V,2,2A,10W(Tc=25°),<100/500nS	2a$	Mit	-
2SD855	Si-NPN	AF,Sw-Pow,60V,1A,30W,-/1µS	17j$	Mat	BD239A,BD241A,2SC1398,2SC3252..
2SD855A	Si-NPN	=2SD855:80V	17j$	-	BD239B,BD241B,2SC2275(A),2SC3252,..
2SD855B	Si-NPN	=2SD855:100V	17j$	-	BD239C,BD241C,2SC2275(A),2SC2528,..
2SD856	Si-NPN	AF,Sw-Pow,60V,3A,35W,-/3µS	17j$	Mat	BD241A,BD535,BD935,2SC3179..
2SD856A	Si-NPN	=2SD856:80V	17j$	-	BD241B,BD537,BD937,2SC3179..
2SD856B	Si-NPN	=2SD856:100V	17j$	-	BD241C,BD539C,BD937,2SD613..
2SD857	Si-NPN	AF,Sw-Pow,60V,4A,40W,-/1,4µS	17j$	Mat	BD243A,BD535,BD949,2SC3179..
2SD857A	Si-NPN	=2SD857:80V	17j$	-	BD243B,BD537,BD951,2SC3179..
2SD857B	Si-NPN	=2SD857:100V	17j$	-	BD243C,BD539C,BD953,2SD613..
2SD858	Si-NPN	AF,Sw-Pow,60V,5A,60W,-/1,4µS	18j$	Mat	BD245A,BDV91,2SD895,2SD718..
2SD858A	Si-NPN	=2SD858:80V	18j$	-	BD245B,BDV93,2SD895,2SD718..
2SD858B	Si-NPN	=2SD858:100V	18j$	-	BD245C,BDV95,2SD895,2SD718..

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2SD859	Si-NPN	AF,Sw-Pow,350/250V,0,75A,35W,-/2μS	17j$	Mat	BUW40(A,B),TIP47..50,2SD1263
2SD859A	Si-NPN	=2SD859:400/300V	17j$	-	BUW40(A,B),TIP48..50,2SD1263A
2SD859B	Si-NPN	=2SD859:450/350V	17j$	-	BUW40(A,B),TIP49..50
2SD860	Si-NPN	AF,Sw-Pow,350/250V,1A,40W,-/2μS	17j$	Mat	BUW40(A,B),TIP47..50,2SC3968
2SD860A	Si-NPN	=2SD860:400/300V	17j$	-	BUW40(A,B),TIP48..50,2SC3968
2SD860B	Si-NPN	=2SD860:450/350V	17j$	-	BUW40(A,B),TIP49..50,2SC3169
2SD861	Si-NPN	AF,Sw-Pow,350/250V,1,5A,45W	17j$	Mat	BUW40(A,B),TIP47..50,2SC3968
2SD861A	Si-NPN	=2SD861:400/300V	17j$	-	BUW40(A,B),TIP48..50,2SC3968
2SD861B	Si-NPN	=2SD861:450/350V	17j$	-	BUW40(A,B),TIP49..50,2SC3169
2SD862	Si-NPN	AF,Sw-Pow,20V,2A,10W	14h$	Mat	BD175,BD233,BD329,BD375,2SD1380
2SD863	Si-NPN	GenP,60V,1A,0,9W,150MHz	7c(9mm)	Sanyo	2SD1014,2SD1146,2SD1207,2SD1292..
2SD864(K)	Si-N-Darl+Di	AF,Sw-Pow,120V,3A,30W,B>1000	17j$	Hit	BDT61C,BDW53D,BDW63D,2SD1147
2SD865	Si-NPN-Darl	Sw,Pow,300/300V,4A,40W,B=1500,<2/20μS	22a$	Fjd	2SD816,2SD977,2SD1073
2SD866	Si-NPN	AF,Sw-Pow,Lo-sat,130V,7A,40W,30MHz	17j$	Mat	2SC4329
2SD866A	Si-NPN	=2SD866:150V	17j$	-	2SC4329
2SD867	Si-NPN	Sw,Pow,130V,10A,100W,3MHz,1,5/5,7μS	23a$	Tos	BD245D,2N3442,2N4348,2SD551..
2SD868	Si-NPN+Diode	TV-HO,1500/600V,2,5A,50W	23a$	Toshiba	BU208D,BU705D,2SD1301,2SD1171..75..
2SD869	Si-NPN+Diode	=2SD868:3,5A	23a$	Tos	BU208D,BU706D,BU4506DX,2SD1171..1175..
2SD870	Si-NPN+Diode	=2SD868:5A	23a$	Tos	BU208D,BU706D,BU4507DX,2SD1171..1175..
2SD871	Si-NPN+Diode	=2SD868:6A	23a$	Tos	BUS08D,BU2508D,2SC3581,2SD1731..
2SD872	Si-NPN	Sw,Pow,500/400V,5A,40W,-/3μS	17j$	Mit	MJE13070,2SC2535,2SC2827,2SC3830..
2SD873	Si-NPN	=2N3773	23a$	Tos	→2N3773
2SD874	Si-NPN	GenP,30V,1A,200MHz	39b	Mat	BC868,BCX68,2SC2883,2SC2982
2SD874A	Si-NPN	=2SD874:60V	39b	-	BCX55..56,2SC3444,2SD1005,2SD1418
2SD874A-Q	Si-NPN	-	39	Mat	→2SD874A
2SD874A-R	Si-NPN	-	39	Mat	→2SD874A
2SD874A-S	Si-NPN	-	39	Mat	→2SD874A
2SD874-Q	Si-NPN	-	39	Mat	→2SD874
2SD874-R	Si-NPN	-	39	Mat	→2SD874
2SD874-S	Si-NPN	-	39	Mat	→2SD874
2SD875	Si-NPN	GenP,80V,0,5A,120MHz	39b	Mat	2SC3438,2SD968(A),2SD1006..1007
2SD875-P	Si-NPN	-	39	Mat	→2SD875
2SD875-Q	Si-NPN	-	39	Mat	→2SD875
2SD875-R	Si-NPN	-	39	Mat	→2SD875
2SD875-S	Si-NPN	-	39	Mat	→2SD875
2SD876	Si-NPN	Hi-beta,200/150V,1A,40W,B>500	17j$	Mat	2SC2317
2SD877	Si-NPN	AF,Sw-Pow,110V,3A,25W,3MHz,1,5/7μS	22a$	Tos	BD241C,BD939,BDW25,BDX25..
2SD878	Si-NPN	=2N3055	23a$	Tos	→2N3055
2SD879	Si-NPN	Lo-sat,30V,3A,0,75W,200MHz	7c	Sanyo	2SC4781,2SD1347,2SD1617
2SD88	Si-NPN	Sw,Pow,300/55V,5A,80W	23a$	Sony	BU104,BU606..608,BUX18(A..C)..
2SD880	Si-NPN	AF,Sw-Pow,60V,3A,30W,3MHz	17j$	Tos	BD241A,BD537,BD937,2SD712..
2SD881	Si-NPN	-		Nec	-
2SD88-1	Si-NPN	=2SD88:100/60V	23a$	-	BD245C,BDX95,2N5758..60,2SD895..
2SD882	Si-NPN	AF,Sw-Pow,Lo-sat,40V,3A,10W,90MHz	14h$	Nec	BD785,MJE240..244,2SD794(A)
2SD88-2	Si-NPN	=2SD88:150/80V	23a$	-	BD245D,BDX11,2N3442,2SD1046..
2SD883	Si-NPN	AF,Sw-Pow,100V,6A,70W	19j$	Nec	2SC2276,2SD587..588,2SD848(A)
2SD88-3	Si-NPN	=2SD88:200/100V	23a$	-	BD245F,DD550A,2SC2262,2SD751..
2SD883A	Si-NPN	=2SD883:120V	19j$	-	2SC2276,2SD587..588,2SD848(A)
2SD884	Si-NPN	TV-HO,330/200V,7A,40W,-/<3μS	17j$	Mat	BU406..408,2SC3173,2SC3590..91..
2SD885	Si-NPN	=2SD884:330/330V	17j$	Mat	BU406..408,2SC3173,2SC3590..91..
2SD886	Si-NPN	AF-Pow,Hi-beta,80/60V,3A,40W,B>500	17j$	Mat	2SD887..888,2SD1157,2SD1943,2SC1983
2SD886A	Si-NPN	=2SD886:100/80V	17j$	-	2SC2316,2SC2491
2SD887	Si-NPN	AF-Pow,Hi-beta,80V,4A,40W,B>500	17j$	Mat	2SC2315..16,2SC2491,2SD1157
2SD888	Si-NPN	AF-Pow,Hi-beta,80V,6A,50W,B>500	17j$	Mat	2SC2315..16,2SC2491,2SD1158
2SD889	Si-NPN	Hi-Ueb,30V,0,1A,150MHz	7c	Mat	2SC3114,2SC3135,2SD1206,2SD1807
2SD88A	Si-NPN	=2SD88:10A,120W	23a$	-	BU109,BUX17A..C,BUY18,BUX43..
2SD88A1	Si-NPN	=2SD88:100/60V,10A,120W	23a$	-	BD545C,BDW21C,2N5632..34,2SD1187,..
2SD88A2	Si-NPN	=2SD88:150/80V,10A,120W	23a$	-	BDX11,2N3442,2SC2837,2SD1047..
2SD88A3	Si-NPN	=2SD88:200/100V,10A,120W	23a$	-	BDW16,MJ15015,2SD753,2SC3855..
2SD890	Si-NPN	Hi-Ueb,100V,0,02A,0,25W,150MHz	7c	Mat	2SC3071,2SC3495,2SD1011
2SD891	Si-NPN-Darl	GenP,30V,0,2A,0,25W,B>2000	7c	Mat	BC517,BC617,BC875,MPSA13..14..
2SD891A	Si-NPN-Darl	=2SD891:60V	7c	-	BC875,BSR50..52,MPSA27..29..
2SD892	Si-NPN-Darl	GenP,30V,0,5A,0,4W,150MHz,B>2000	7c	Mat	BC617,BC875,BSR50..52,MPSA27..29..
2SD892A	Si-NPN-Darl	=2SD892:60V	7c	-	BC875,BSR50..52,MPSA27..29..

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2SD893	Si-NPN-Darl	GenP,30V,1A,0,75W,150MHz,B>2000	7c	Matsushita	BC617,BC875,BSR50..52,MPSA27..29..
2SD893A	Si-NPN-Darl	=2SD893:60V	7c	-	BC875,BSR50..52,MPSA27..29..
2SD894	Si-NPN-Darl	AF,Sw-Pow,30V,1,5A,10W,120MHz	14h$	Sanyo	2SC4341,2SD985..986,2SD1379,2SD1438
2SD895	Si-NPN	AF,Sw-Pow,100V,6A,60W,15MHz	18j$	Sanyo	BD245C,BDV95,2SC2681,2SD718..
2SD896	Si-NPN	AF,Sw-Pow,120V,7A,70W,15MHz	18j$	Sanyo	BD245C,2SC2681,2SC2837,2SD718..
2SD897(A)	Si-NPN+Diode	TV-HD,1500V,1,5A,50W	23a$	Hitachi	BU208D,BU705D,2SD1171..75,2SD1301..
2SD898(A,B)	Si-NPN+Diode	=2SD897:3..3,5A	23a$	Hit	BU208D,BU706D,2SD1171..75,2SD1729..
2SD899(A)	Si-NPN+Diode	=2SD897:4..5A	23a$	Hit	BU208D,BU706D,2SD1171..75,2SD1729..
2SD90	Si-NPN	AF,Sw-Pow,30V,3A,20W,-/3,8µS	22a$	Sak	BD241,BD533,BD933,2SD877..
2SD900(A,B)	Si-NPN+Diode	=2SD897:5..6A	23a$	Hit	BU208D,BU508D,2SD1171..75,2SD1731..
2SD901	Si-NPN	AF,Sw-Pow,200V,2A,25W	17j$	Nec	BD239F,2SC2660,2SD760,2SD1138..
2SD902	Si-NPN	Sw,Pow,350V,4A,80W	23a$	Sanyo	BUX16B,2SC2624,2SC3083
2SD903	Si-NPN+Diode	CTV-HD,1500/600V,7A,50W	23a$	Fui,Say	BU508D,2SD994,2SC3682,2SD1732..
2SD904	Si-NPN+Diode	CTV-HD,1500/600V,7A,50W	23a$	Fui,Say	BU508D,2SD994,2SC3682,2SD1732..
2SD905	Si-NPN	TV-HD,1400/650V,8A,50W	23a$	Hitachi	BU508(A),2SC3027,2SC4801,2SD1279..
2SD906	Si-NPN	TV-HD,1400/650V,8A,50W	23a$	Hitachi	BU508(A),2SC3027,2SC4801,2SD1279..
2SD907	Si-NPN	AF,Sw-Pow,80V,10A,80W,<1/3µS	18j$	Fjd	BD245B,BD545B,BDV93,2SC3256..
2SD908	Si-NPN	=2SD907:120V	18j$	Fjd	BD245C,BD545D,2SC2681,2SD1047..
2SD909	Si-NPN	AF,Sw-Pow,80V,15A,80W	18j$	Fjd	BD249B,BD545B,BD745B
2SD91	Si-NPN	=2SD90:60/40V	22a$	Sak	BD241A,BD535,BD935,2SD877..
2SD910	Si-NPN	=2SD909:120V	18j$	Fjd	BD249C,BD545D,BD745D
2SD911	Si-NPN	AF,Sw-Pow,80V,15A,100W	23a$	Fjd	BD249B,BD317,BD545B,BD745B..
2SD912	Si-NPN	=2SD911:120V	23a$	Fjd	BD249C,BD545D,BD745D,2N5630..31,..
2SD913	Si-NPN	Sw,Pow,200/80V,25A,150W,<1/2,9µS	23a$	Fujitsu	BDW36,BUV11..12,BUX11..12..
2SD914	Si-NPN	=2SD913:200/120V	23a$	Fjd	BDW36,BUV11..12,BUX11..12..
2SD915	Si-NPN-Darl	Sw,Pow,600/600V,30A,200W,B=300	?74	Fjd	-
2SD916	Si-NPN-Darl	Sw,Pow,Sw-Reg,60V,7A,30W,B>800	17j$	Fjd	BD645,BD897,BDW73A,BDX53A..
2SD917	Si-NPN	TV-HD,330/200V,7A,70W	18j$	Mat	(BU426(A),BU926)
2SD918	Si-NPN	AF,Sw-Pow,250V,2A,80W	19j$	Nec	-
2SD919	Si-NPN	GenP,30V,0,5A,0,4W,200MHz	40c	Mat	BC337..338,BC635,BC637,2SC3377..
2SD92	Si-NPN	=2SD90:100/55V	22a$	Sak	BD241C,BD937,2SD712,2SD877..
2SD920	Si-NPN-Darl	AF,Sw-Pow,200/180V,5A,100W,B>700	23a$	Fjd	2SD929,2SD931,2SD1090,2SD1122..23
2SD921	Si-NPN-Darl	=2SD920:80W	18j$	Fjd	2SD1090,2SD1122..23
2SD922	Si-NPN-Darl	AF,Sw-Pow,150V,10A,100W,B>700	23a$	Fjd	2SD1123,2SD1210
2SD923	Si-NPN-Darl	=2SD922:80W	18j$	Fjd	2SD1123,2SD1210
2SD926	Si-NPN	AF,Sw-Pow,50V,4A,30W	17j$	Hit	BD243,BD535,BD949,2SC3179..
2SD927	Si-NPN	=2SD926:60V	17j$	Hit	BD243A,BD535,BD949,2SC3179..
2SD928	Si-NPN	=2SD926:80V	17j$	Hit	BD243B,BD537,BD951,2SC3179..
2SD929	Si-NPN-Darl	AF,Sw-Pow,200/180V,5A,80W,B>700	23a$	Fjd	2SD776,2SD920..921,2SD931,2SD1123
2SD93	Si-NPN	=2SD90:150/150V	22a$	Sak	BD241D,2SD772(A,B)
2SD930	Si-NPN-Darl	AF,Sw-Pow,200/180V,5A,30W,B>700	17j$	Fjd	2SD1023,2SD1025
2SD931	Si-NPN-Darl	AF,Sw-Pow,200/180V,5A,50W,B>700	23a$	Fjd	2SD776,2SD920..921,2SD929,2SD1123
2SD932	Si-NPN-Darl	Sw,Pow,500/300V,6A,80W,B=1500	20j$	Hit	-
2SD933(H)	Si-N-Darl+Di	300/300V,6A,80W,B=1500	23a$	Hitachi	(2SD650,2SD706,2SD1043,2SD1461)
2SD934(K)	Si-N-Darl+Di	Sw,Pow,300/300V,6A,80W,B=1500	20j$	Hit	2SD932
2SD935	Si-NPN	Sw,Pow,250V,5A,60W	18j$	Mat	TIP55A..58A,2SC2305,2SC2624,2SD1150
2SD936	Si-NPN-Darl	Sw,Pow,300/250V,30A,400W,B>150	?74	Tos	-
2SD937	Si-NPN-Darl	=2SD936:400/350V	?74	Tos	-
2SD938	Si-NPN-Darl	=2SD936:600/450V	?74	Tos+	-
2SD939	Si-NPN-Darl	Sw,Pow,300/250V,40A,400W,B>150	?74	Tos	-
2SD94	Si-NPN	=2SD90:200/80V	22a$	Sak	BD241F,2SD772A,B
2SD940	Si-NPN-Darl	=2SD939:400/350V	?74	Tos	-
2SD941	Si-NPN-Darl	=2SD939:600/450V	?74	Tos	-
2SD942	Si-NPN-Darl	Sw,Pow,300/250V,50A,400W,B>150	?74	Tos	-
2SD943	Si-NPN-Darl	=2SD942:400/350V	?74	Tos	-
2SD944	Si-NPN-Darl	AF,Sw-Pow,40V,2A,5W,150MHz,B>4000	14h$	Rhm	2SD1379,2SD1438
2SD946	Si-NPN-Darl	AF,Sw-Pow,30V,1A,150MHz,B>4000	14h$	Mat	BD477A,B,BD875,BDX42,2SD1379..
2SD946A	Si-NPN-Darl	=2SD946:60V	14h$	-	BD875,BDX42..44,2SC4340,2SD1376..
2SD946B	Si-NPN-Darl	=2SD946:100V	14h$	-	BD879,BDX44,2SD1376,2SD1953
2SD947(F)	Si-NPN-Darl	AF,Sw-Pow,40V,2A,5W,150MHz,B>4000	14b	Rhm	2SD1509,(2SD1379,2SD1438)
2SD948	Si-NPN	TV-HD,1600V,1A,25W	22a$	Mat	BU505,2SD470,2SD1575
2SD949	Si-NPN	TV-HD,1500V,2A,40W	23a$	Matsushita	BU205..206,BU705,2SC1922,2SD818..
2SD95	Si-NPN	-		Sak	-
2SD950	Si-NPN+Diode	TV-HD,1500V,3A,42W	23a$	Matsushita	BU208D,2SC3480,2SD993,2SD1171..75,..

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2SD951	Si-NPN+Diode	TV-HD, 1500V, 3A, 65W	23a$	Matsushita	BU208D, 2SC3480, 2SD993, 2SD1171..75,..
2SD952	Si-NPN+Diode	TV-HD, 1500V, 3A, 70W	23a$	Matsushita	BU706D, 2SC3480, 2SD1173..75, 2SD1729..
2SD953	Si-NPN+Diode	TV-HD, 1500V, 5A, 95W	23a$	Matsushita	BU2508D, 2SD1174..75, 2SD1730..31..
2SD954	Si-NPN	TV-HD, 1500V, 5A, 95W	23a$	Matsushita	BU508A, BU2508A
2SD955	Si-NPN	AF, 120V, 0,05A, 0,625W	7e	Hit	2SC1890A, 2SC2240, 2SC2363, 2SC3245(A)..
2SD956	Si-NPN+Diode	TV-HD, 1500V, 2,5A, 50W	23a$	Hitachi	BU208D, 2SC3479, 2SD993, 2SD1171..75,..
2SD957	Si-NPN+Diode	TV-HD, 1500V, 6A, 50W	23a$	Hitachi	(2SD903..904, 2SD994)
2SD957A	Si-NPN+Diode	=2SD957:7A	23a$	-	(2SD903..904, 2SD994)
2SD958	Si-NPN	AF, LN, 120V, 0,02A, 0,4W, 200MHz	9c	Mat	2SC1775A, 2SC2240, 2SC2389, 2SC2459..
2SD959	Si-NPN	AF, Sw-Pow, Lo-sat, 130V, 3A, 30W, 30MHz	17j$	Mat	2SD1528
2SD96	Ge-NPN	AF-Dr/Out, 25V, 0,25A, 0,3W	2a	Hit	AC127, AC176, AC187, 2SD30, 2SD72
2SD960	Si-NPN	=2SD959:4A, 35W	17j$	Mat	2SD866
2SD961	Si-NPN	=2SD959:5A, 40W	17j$	Mat	2SD866
2SD962	Si-NPN-Darl	AF, Sw-Pow, 200V, 5A, 80W, B=3000	23a$	Sak	2SD776, 2SD920..921, 2SD929, 2SD931..
2SD963	Si-NPN-Darl	=2SD962:100W	23a$	-	2SD776, 2SD920..921, 2SD929, 2SD931..
2SD964	Si-NPN	-		Mit	-
2SD965	Si-NPN	AF, 40V, 5A, 0,75W, 150MHz	7c	Mat	2SC3671, 2SD1145, 2SD1244, 2SD2249..
2SD966	Si-NPN	=2SD965:1W	7c(9mm)	Mat	2SD1934, 2SD1961
2SD967	Si-NPN-Darl	GenP, 30V, 0,2A, 0,4W, B=7000	9c	Mat	BC517, BC617, BC875, MPSA13..13..
2SD968	Si-NPN	AF, 100V, 0,5A, 120MHz	39b	Mat	BCX56, 2SC2881, 2SC3438, 2SD1005..1007
2SD968A	Si-NPN	-	39	Mat	→2SD968A
2SD968A-P	Si-NPN	-	39	Mat	→2SD968A
2SD968A-Q	Si-NPN	-	39	Mat	→2SD968A
2SD968A-R	Si-NPN	-	39	Mat	→2SD968A
2SD968A-S	Si-NPN	-	39	Mat	→2SD968A
2SD968-P	Si-NPN	-	39	Mat	→2SD968
2SD968-Q	Si-NPN	-	39	Mat	→2SD968
2SD968-R	Si-NPN	-	39	Mat	→2SD968
2SD968-S	Si-NPN	-	39	Mat	→2SD968
2SD969	Si-NPN	AF, Lo-sat, 25V, 0,5A, 0,6W, 150MHz	9c	Mat	2SD1012, 2SD1302, 2SD1207, 2SD1246..47..
2SD970(K)	Si-N-Darl+Di	AF, Sw-Pow, 120V, 8A, 40W, B>1000	17j$	Hit	BD651, BDT21, BDW73D, BDX53D
2SD971	Si-NPN-Darl	Sw, Pow, 300/300V, 6A, 50W, B=2000	17j$	Sak	BU910..912, 2SD1088..1089, 2SD1307..
2SD972	Si-NPN-Darl	AF, Sw-Pow, 50V, 4A, 30W, B=3000	17j$	Sak	BD715, BDW23A, BDW53A, BDW63A..
2SD973	Si-NPN	AF-Dr/Out, 30V, 1A, 1W, 200MHz	9c	Mat	BC337..338, BC635, BC637, 2SD1225..
2SD973A	Si-NPN	=2SD973:60V	9c	-	BC337A, BC635, BC637, 2SD1616..
2SD974	Si-NPN	Sw, TV, 120V, 1A, 0,9W	7c(9mm)	Hit	2SC2383, 2SC3228, 2SD667(A), 2SD1812..
2SD975	Si-NPN	Sw, Pow, TV-HD, 150/60V, 2A	14h$	Hit	2SD781
2SD976	Si-NPN	TV-HD, 300/120V, 7A, 50W	17j$	Hit	BU406..408, 2SD884..885, 2SD1163..
2SD976A	Si-NPN	=2SD976:350/150V	17j$	-	BU406, BU408, 2SC3175, 2SC3591
2SD977	Si-NPN-Darl	Sw, Pow, 450/350V, 4A, 40W, B=300, <1/25µS	17j$	Sanyo	BU911..912, 2SD987, 2SD1072, 2SD1245,..
2SD978	Si-NPN-Darl	=2SD977:5A, B>400	17j$	-	BU911..912, 2SD987, 2SD1072, 2SD1245,..
2SD979	Si-NPN-Darl	Sw, Pow, 450/350V, 10A, 100W, B=900	18j$	Sanyo	BU921..922, BUW81(A), 2SD685..
2SD980	Si-NPN-Darl	=2SD979:7A	18j$	Sanyo	BU921..922, BUW81(A), 2SD707..
2SD981	Si-NPN-Darl	Reg-Pow, 200/180V, 5A, 100W, B=3000	23a$	Fujitsu	2SD776, 2SD920..921, 2SD929, 2SD931..
2SD982	Si-NPN-Darl	=2SD981:40W	17j$	Fjd	2SD930, 2SD1023, 2SD1025, 2SD1756
2SD983	Si-NPN-Darl	=2SD981:150/100V, 40W	17j$	Fjd	BDX53F, 2SD830, 2SD1128, 2SD1169..
2SD985	Si-N-Darl+Di	AF, Sw-Pow, 150/60V, ±1,5A, 10W, B>2000	14h$	Nec	2SD2019
2SD986	Si-N-Darl+Di	=2SD985:150/80V	14h$	Nec	2SD2019
2SD987	Si-N-Darl+Di	Sw, Pow, 500/400V, ±5A, 40W, B>200	17j$	Nec	BU912, 2SD798..799, 2SD1245
2SD988..989	Si-NPN	-		Nec	-
2SD990(K)	Si-NPN-Darl	AF, Sw-Pow, 100V, 3A, 30W, B>500	17j$	Hit	BDW23C, BDW53C, BDW63C, 2SD837B..
2SD991(K)	Si-N-Darl+Di	300/300V, 6A, 50W, B>500	17j$	Hit	(2SD971, 2SD1071, 2SD1088..89, 2SD1113+)
2SD992(Z)	Si-NPN	AF, Sw-Pow, Lo-sat, 30V, 2A, 10W	30j$	Nec	2SC3076, 2SD1801..02
2SD993	Si-NPN+Diode	CTV-HD, 1500/600V, 3A, 50W	23a$	Sanyo	BU208D, 2SC3480, 2SD1171..75, 2SD1729..
2SD994	Si-NPN+Diode	CTV-HD, 1500/600V, 8A, 50W	23a$	Sanyo	BU508D, BU2508D, 2SC3683
2SD995	Si-NPN+Diode	CTV-HD, 2500/900V, 3A, 50W	23a$	Sanyo	-
2SD996	Si-NPN	-		Tos	-
2SD997	Si-NPN	AF, Sw-Pow, 250/200V, 10A, 200W, 15MHz	23a$	Nec	BUX17(A..C), 2SC1586, 2SD555, 2SD583
2SD998	Si-NPN-Darl	AF, Sw-Pow, 100V, 1,5A, 10W, B=7000	14h$	Nec	BD681, 2SD1376, 2SD1953
2SD999	Si-NPN	GenP, 30V, 1A, 130MHz	39b	Nec	BC868, BCX54, BCX68, 2SC2883..
2SD999-CK	Si-NPN	-	39	Nec	→2SD999
2SD999-CL	Si-NPN	-	39	Nec	→2SD999
2SD999-CM	Si-NPN	-	39	Nec	→2SD999
2SF1168(A)	Thy-50Hz	200(A=400)V, 6A, Igt/Ih<25/15mA	22a$	Mat	MCR218..TAG625-..TAG651-..

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2SF1188	Thy-Fast	TV-HD, +650V, 3,2A(Tc=60°C), Igt<30mA	22a$	Sanyo	S3703, (TD3F700H, TD4F700H,..)
2SF1189	Thy-Fast	TV-HD, +600V, 3,2A(Tc=60°C), Igt<40mA	22a$	Sanyo	S3702, (TD3F800R, TD4F800R,..)
2SF1418C..G	Thy-Fast	200..600V, 3,2A(60°), Igt<35mA, <4,3µS, C=200, D=300, E=400, F=500, G=600V..	22a$	Sanyo	BTW27S/.., T3S.., TAG670..671S-..
2SF1420D..G	Thy-Fast	300..700V, 3,2A(75°), Igt/Ih<35/<30mA, D=300, E=400, F=500, G=600, H=700V..	22a$	Sanyo	BTW27S/.., T3S.., TAG670..671S-..
2SF1450-200..600	Thy-50Hz	=CP8C..G	-	Hit	→CP8..
2SF1451-200..600	Thy-50Hz	=CP9C..G	-	Hit	→CP9..
2SH11	UJT-P	35V, 50mA, Ip<12µA, Iv>7mA	2o	Nec, Tho	-
2SH13	UJT-P	55V, 50mA, Ip<6µA, Iv>11mA	2o	Tos	-
2SH15	UJT-P	30V, 50mA, Ip<12µA, Iv>7mA	2o	Tos	-
2SH16(A)	UJT-P	30V, 50mA, Ip<12µA, Iv>4mA	7s	Nec, Tho	2N2646P
2SH20	UJT-P	55V, 50mA, Ip<3,5µA, Iv>6mA	2o	Tos	-
2SH22	UJT-P	25V, 50mA, Ip<4µA, Iv>4mA	2o	Tos	2SH21
2SH23	UJT-P	25V, 100mA, Ip<4µA, Iv>7mA	2o	Nec	2SH20
2SH24	UJT-P	=2SH23: Ip<12?A	2o	Nec	-
2SH25	UJT-P	=2SH23: 75mA, 0,3W	7o	Nec	-
2SJ0398	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, 10W, <0,4Ω(5A)	30c$	Mat	2SJ191, 2SJ194, 2SJ326
2SJ0536	MOS-P-FET-e	V-MOS, LogL, 30V, 0,1A, <75Ω	35a(2mm)	Mat	2SJ463
2SJ100	MOS-P-FET-e	=2SJ99: 160V	20c$	Hit	(2SJ83)
2SJ101	MOS-P-FET-e	V-MOS, 40V, 5A, 30W, <0,4e, 60/100nS	17c$	Hit	BUZ172, IRF9521, IRF9523, 2SJ153,..
2SJ102	MOS-P-FET-e	=2SJ101: 60V	17c$	Hit	BUZ172, IRF9521, IRF9523, 2SJ153,..
2SJ103	P-FET	Sw, GenP, 50V, Idss>1,2mA, Up<6V	7e	Tos	2N5460, 2N5463, 2SJ105
2SJ104	P-FET	Sw, GenP, 25V, Idss>2,6mA, Up<2V	7a	Tos	2SJ107..108
2SJ105	P-FET	=2SJ103:	41e	Tos	2N5460, 2N5463, 2SJ103
2SJ106	P-FET	=2SJ103: SMD	35f	Tos	-
2SJ106-BL	P-FET	-	35	Tos	→2SJ106
2SJ106-GR	P-FET	-	35	Tos	→2SJ106
2SJ106-Y	P-FET	-	35	Tos	→2SJ106
2SJ107	P-FET	=2SJ104:	41a	Tos	2SJ104, 2SJ108
2SJ108	P-FET	GenP, LN, 25V, Idss>1mA, Up<2V	41a	Tos	2SJ104, 2SJ107
2SJ109	P-FET	Dual, 30V, Idss=2,6..20mA, Up<2V	7-SQP/bp1	Tos	-
2SJ11	P-FET	GenP, 20V, Idss=0,05..0,9mA, Up<5V	5g	Tos	2N2606, 2N5797
2SJ110	P-FET	Sw, GenP, 25V, Idss=5..30, Up<2V	7a	Tos	2SJ72
2SJ111	P-FET	AF, Sw, LN, 25V, Idss=5..30, Up<2V	7a	Tos	2SJ72
2SJ112	MOS-P-FET-e	V-MOS, 100V, 10A, 100W, <0,35Ω(5A)	23a$	Hit	2SJ131, 2SJ200
2SJ113	MOS-P-FET-e	=2SJ112:	18c$	Hit	2SJ131, 2SJ200
2SJ114	MOS-P-FET-e	=2SJ112: 200V, 8A	18c$	Hit	-
2SJ115	MOS-P-FET-e	V-MOS, AF-Pow, 160V, 8A, 100W, <1,4©	18c$	Tos	2SJ114, 2SJ119
2SJ116	MOS-P-FET-e	V-MOS, 400V, 8A, 125W, <2,25e, 60/220nS	23a$	Hit	-
2SJ117	MOS-P-FET-e	V-MOS, 400V, 2A, 40W, <7Ω(5A), 35/80nS	17c$, d*(?)	Hit	-
2SJ118	MOS-P-FET-e	V-MOS, 140V, 8A, 100W, <4Ω(5A), 70/160nS	18c$	Hit	2SJ114..115
2SJ119	MOS-P-FET-e	=2SJ118: 160V	18c$	Hit	2SJ114..115
2SJ12	P-FET	=2SJ11: Idss=0,09..0,9mA	5g	Tos	2N2606, 2N5797
2SJ120(L,S)	MOS-P-FET-e	V-MOS, 40V, 2A, 10W, <1,5Ω(5A), 35/40nS	30c$	Hit	2SJ128, 2SJ133, 2SJ191, 2SJ194
2SJ122	MOS-P-FET-e	V-MOS, 60V, 10A, 50W, <0,2Ω, 80/200nS	17c$	Hit	IRF9531, IRF9533, 2SJ136, 2SJ169,..
2SJ123	MOS-P-FET-e	V-MOS, Pow, 70V, 10A, 30W, <0,4Ω	17c$	Tos	2SJ170, 2SJ138
2SJ125	P-FET	GenP, 50V, Idss=1..12mA, Up<6V	35f	Mit	-
2SJ125-C	P-FET	-	35	Mit	→2SJ125
2SJ125-D	P-FET	-	35	Mit	→2SJ125
2SJ125-E	P-FET	-	35	Mit	→2SJ125
2SJ126	MOS-P-FET-e	V-MOS, Pow, 60V, 10A, 40W, <0,4Ω(5A)	17c	Tos	2SJ137, 2SJ147, 2SJ175, 2SJ236
2SJ127	MOS-P-FET-e*	V-MOS, 120V, 10A, 50W, 0,25Ω, 110/240nS	17c$	Hit	IRF9640, IRF9641
2SJ128(Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±2A, 20W, <1Ω(5A)	30c$	Nec	2SJ194
2SJ129	P-FET	AF-Pre, 50V, 20mA, Idss=0,5..14mA, Up<3V	40e	Mat	2N5021, 2SJ74
2SJ13	P-FET	GenP, 20V, Idss=1..12mA, Up<6V	2a&	Tos	-
2SJ130(L,S)	MOS-P-FET-e*	V-MOS, 300V, 1A, 20W, <8,5Ω, 35/80nS	30c$	Hit	-
2SJ131	MOS-P-FET-e	V-MOS, Sw, Pow, 170V, 10A, 100W	18c($)	Son	2SJ200
2SJ132(Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 30V, ±2A, 20W, <0,4Ω(5A)	30c$	Nec	2SJ120, 2SJ191
2SJ133(Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 60V, ±2A, 20W, <0,8Ω(5A)	30c$	Nec	2SJ191
2SJ134	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±6A, 40W, <0,6Ω(3,5A)	17c$	Nec	IRF9630..9633
2SJ135	MOS-P-FET-e	=2SJ134: Iso, ±5A, 30W	17c	Nec	2SJ154
2SJ136	MOS-P-FET-e	V-MOS, Sw, Pow, 60V, ±12A, 40W, <0,3Ω(6,5A)	17c$	Nec	IRF9541, IRF9543, 2SJ140, 2SJ173
2SJ137	MOS-P-FET-e	=2SJ136: Iso, ±10A, 30W	17c	Nec	2SJ147, 2SJ175
2SJ138	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±12A, 60W, <0,3Ω(6,5A)	17c$	Nec	IRF9540, IRF9542, 2SJ127
2SJ139	MOS-P-FET-e	=2SJ138: Iso, ±10A, 35W	17c	Nec	2SJ274

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2SJ140	MOS-P-FET-e	V-MOS,Sw,Pow,60V,±19A,60W,<0,2Ω(10A)	17c$	Nec	2SJ174,2SJ221
2SJ141	MOS-P-FET-e	=2SJ140:Iso,n13A,35W	17c	Nec	2SJ176,2SJ293
2SJ142	MOS-P-FET-e	V-MOS,Sw,Pow,100V,n13A,35W,<0,2Ω(10A)	17c	Nec	2SJ222
2SJ143	MOS-P-FET-e	V-MOS,Sw,Pow,60V,±16A,35W,<0,15Ω(10A)	17c	Nec	2SJ176..177,2SJ240
2SJ144	P-FET	GenP,50V,Idss=1,2..14mA,Up<6V	35f(2mm)	Tos	-
2SJ144-BL	P-FET	-	35(2mm)	Tos	→2SJ144
2SJ144-GR	P-FET	-	35(2mm)	Tos	→2SJ144
2SJ144-Y	P-FET	-	35(2mm)	Tos	→2SJ144
2SJ145	P-FET	=2SJ125:	35f(2mm)	Mit	-
2SJ145-C	P-FET	-	35(2mm)	Mit	→2SJ145
2SJ145-D	P-FET	-	35(2mm)	Mit	→2SJ145
2SJ145-E	P-FET	-	35(2mm)	Mit	→2SJ145
2SJ146	MOS-P-FET-e	V-MOS,50V,0,1A,<40/60nS,<150Ω	35a	Mat	BSS84,2SJ185,2SJ209..210
2SJ147	MOS-P-FET-e	V-MOS,60V,12A,40W,0,2Ω,65/160nS	17c	Tos	2SJ141,2SJ175..176,2SJ265
2SJ148	MOS-P-FET-e	Sw,60V,0,2A,0,4W,<2Ω(50(A),14/100nS	7c	Tos	BST100
2SJ15	P-FET	GenP,18V,Idss=1,5mA,Up<6V	2b&	Fui	2N5460,2N5463,2SJ103,2SJ105
2SJ151	MOS-P-FET-e*	V-MOS,Sw,Pow,100V,±3A,35W,<1,2Ω(1,5A)	17c$	Nec	IRF9510,IRF9620..9623
2SJ152	MOS-P-FET-e*	=2SJ151:Iso,30W	17c	Nec	2SJ135,2SJ157
2SJ153	MOS-P-FET-e*	V-MOS,Sw,Pow,60V,±6A,40W,<0,6Ω(3,5A)	17c$	Nec	-
2SJ154	MOS-P-FET-e*	=2SJ153:Iso,±5A,30W	17c	Nec	2SJ137,2SJ147,2SJ175,2SJ236,2SJ390..
2SJ155	MOS-P-FET-e	V-MOS,Sw,Pow,50V,3A,30W,<0,65Ω(5A)	17c	Mat	2SJ152
2SJ156	MOS-P-FET-e	V-MOS,Sw,Pow,50V,5A,30W,<0,22Ω(5A)	17c	Mat	2SJ135,2SJ154
2SJ157	MOS-P-FET-e	V-MOS,Sw,Pow,100V,3A,30W,<1,6Ω(5A)	17c	Mat	2SJ135,2SJ152
2SJ158	MOS-P-FET-e	V-MOS,Sw,Pow,100V,5A,30W,<0,55Ω(5A)	17c	Mat	2SJ135,2SJ154
2SJ159	MOS-P-FET-e	V-MOS,Sw,Pow,160V,3A,30W,<1Ω(5A)	17c	Mat	2SJ306
2SJ16	P-FET	GenP,18V,Idss=1,5mA,Up<6V	2b&	Fui	2N5460,2N5463,2SJ103,2SJ105
2SJ160	MOS-P-FET-e*	V-MOS,Sw,Pow,120V,7A,100W,230/110nS	18d*,c$(?)	Hit	(2SJ115,2SJ118..119)
2SJ161	MOS-P-FET-e*	=2SJ160:140V	18d*,c$(?)	Hit	(2SJ115,2SJ118..119)
2SJ162	MOS-P-FET-e*	=2SJ160:160V	18d*,c$(?)	Hit	(2SJ115,2SJ119)
2SJ163	P-FET	-	35	Mat	→2SJ163
2SJ163-O	P-FET	-	35	Mat	→2SJ163
2SJ163-P	P-FET	-	35	Mat	→2SJ163
2SJ163-Q	P-FET	-	35	Mat	→2SJ163
2SJ163-R	P-FET	-	35	Mat	→2SJ163
2SJ164	P-FET	65V,20mA,Idss=0,2..6mA,Up<3,5V	40e	Mat	2N5020
2SJ165	MOS-P-FET-e*	V-MOS,50V,±0,1A,0,25W,<50Ω(20mA)	40c	Nec	BSS110,2SJ148
2SJ166	MOS-P-FET-e*	-	35	Nec	→2SJ166
2SJ167	MOS-P-FET-e	=2SJ148:0,3W	41c	Tos	BST100
2SJ168	P-FET	-	35	Tos	→2SJ168
2SJ169	MOS-P-FET-e	V-MOS,Sw,Pow,60V,12A,50W,<0,35Ω(6,5A)	17c$	Hit	2SJ122..123,2SJ172
2SJ17	P-FET	AF,LN,20V,Idss>0,11mA	40d	Son	-
2SJ170	MOS-P-FET-e	V-MOS,Sw,Pow,80V,12A,50W,<0,35Ω(6,5A)	17c$	Hit	2SJ127,2SJ138
2SJ171	MOS-P-FET-e	V-MOS,Sw,Pow,50V,9,7A,40W,<0,28Ω(5,5A)	17c$	Hit	BUZ171,2SJ122..123,2SJ136,2SJ172
2SJ172	MOS-P-FET-e*	V-MOS,LogL,60V,10A,40W,<0,18Ω(5A)	17c$	Hit	2SJ290,2SJ539,2SJ540
2SJ173	MOS-P-FET-e*	V-MOS,LogL,60V,15A,50W,<0,11Ω(5A)	17c$	Hit	2SJ221,2SJ290,2SJ541,2SJ542
2SJ174	MOS-P-FET-e*	V-MOS,LogL,60V,20A,75W,<0,085Ω(10A)	17c$	Hit	2SJ221,2SJ291,2SJ328,2SJ543
2SJ175	MOS-P-FET-e*	=2SJ172:Iso,25W	17c	Hit	2SJ236
2SJ176	MOS-P-FET-e*	=2SJ173:Iso,30W	17c	Hit	2SJ293,2SJ321
2SJ177	MOS-P-FET-e*	=2SJ174:Iso,35W	17c	Hit	2SJ294,2SJ322,2SJ330,2SJ374
2SJ178	MOS-P-FET-e*	V-MOS,Sw,30V,±1A0,75W,<1Ω(0,5A)	7b	Nec	2SJ196
2SJ179	MOS-P-FET-e*	-	39	Nec	→2SJ179
2SJ18	P-FET	V-FET-Pow,170V,5A,63W,16Ω	23a$	Son	-
2SJ180	MOS-P-FET-e*	=2SJ178:1W	9c	Nec	2SJ196
2SJ181(L,S)	MOS-P-FET-e*	V-MOS,600V,0,5A,20W,<25Ω(0,5A)	30c$	Hit	-
2SJ182(L,S)	MOS-P-FET-e*	V-MOS,LogL,60V,3A,20W,<0,4Ω(5A)	30c$	Hit	2SJ235
2SJ183	MOS-P-FET-e*	V-MOS,LogL,60V,5A,20W,<0,35Ω(2,5A)	30c$	Tos	2SJ192,2SJ245,2SK279
2SJ184	MOS-P-FET-e*	V-MOS,LogL,50V,±0,1A,0,25W,<40Ω	40c	Nec	BSS110
2SJ185	MOS-P-FET-e*	-	35	Nec	→2SJ185
2SJ186	MOS-P-FET-e*	V-MOS,200V,0,5A,<12Ω(0,25A),12/32nS	39b	Hit	-
2SJ187	MOS-P-FET-e*	V-MOS,LogL,30V,1A,<0,75Ω(0,5A)	39b	Sanyo	2SJ190,2SJ278
2SJ188	MOS-P-FET-e*	V-MOS,LogL,30V,2A,20W,<0,3Ω(5A)	30c$	Sanyo	2SJ191,2SJ194
2SJ189	MOS-P-FET-e*	V-MOS,LogL,30V,4A,30W,<0,12Ω(5A)	30c$	Sanyo	2SJ192,2SJ245,2SJ279
2SJ19	P-FET	V-FET,AF,140V,0,1A,0,8W	2a$	Nec	-
2SJ190	MOS-P-FET-e*	V-MOS,LogL,60V,1A,<1,2Ω(0,5A)	39b	Sanyo	2SJ278

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2SJ191	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 20W, <0,45Ω(5A)	30c$	Sanyo	2SJ235
2SJ192	MOS-P-FET-e*	V-MOS, LogL, 60V, 4A, 30W, <0,2Ω(5A)	30c$	Sanyo	2SJ245, 2SJ279
2SJ193	MOS-P-FET-e*	V-MOS, LogL, 100V, 1A, <2,4Ω(0,5A)	39b	Sanyo	2SJ508
2SJ194	MOS-P-FET-e*	V-MOS, LogL, 100V, 2A, 20W, <0,95Ω(5A)	30c$	Sanyo	2SJ195
2SJ195	MOS-P-FET-e*	V-MOS, LogL, 100V, 4A, 30W, <0,4Ω(5A)	30c$	Sanyo	-
2SJ196	MOS-P-FET-e*	V-MOS, Sw, 60V, ±1A 0,75W, <1Ω(0,5A)	7b	Nec	2SJ353
2SJ197	MOS-P-FET-e	-	39	Nec	→2SJ197
2SJ198	MOS-P-FET-e*	V-MOS, Sw, 100V, ±0,5A, 0,75W, <2Ω(0,5A)	7b	Nec	2SJ231
2SJ199	MOS-P-FET-e*	-	39	Nec	→2SJ199
2SJ20	P-FET	V-FET-Pow, 100V, 10A, 100W, 10Ω	23a$	Nec	-
2SJ200	MOS-P-FET-e	V-MOS, AF-Pow, 180V, 10A, 120W	18c$	Tos	-
2SJ201	MOS-P-FET-e	V-MOS, AF-Pow, 200V, 12A, 150W	77c$	Tos	-
2SJ202	MOS-P-FET-e*	V-MOS, Sw, 16V, ±0,1A, <30e(10A)	35a(2mm)	Nec	-
2SJ203	MOS-P-FET-e*	V-MOS, Sw, 16V, ±0,2A, <10e(10A)	35a	Nec	BSS84, 2SJ185
2SJ204	MOS-P-FET-e*	V-MOS, Sw, 30V, ±0,2A, <8Ω(10mA)	35a	Nec	BSS84, 2SJ185
2SJ205	MOS-P-FET-e*	V-MOS, Sw, 16V, ±0,5A, <3Ω(0,5A)	39b	Nec	2SJ212
2SJ206	MOS-P-FET-e*	V-MOS, Sw, 30V, ±0,5A, <3Ω(0,5A)	39b	Nec	2SJ212
2SJ207	MOS-P-FET-e*	V-MOS, Sw, 16V, ±1A <1,5Ω(0,5A)	39b	Nec	2SJ190, 2SJ197, 2SJ238
2SJ208	MOS-P-FET-e*	V-MOS, Sw, 16V, ±2A, <1Ω(5A)	39b	Nec	-
2SJ209	MOS-P-FET-e*	V-MOS, Sw, 100V, ±0,1A, <60e(10mA)	35a	Nec	-
2SJ21	P-FET	V-FET-Pow, 160V, 15W, Idss=30..300	22a$	Nec	-
2SJ210	MOS-P-FET-e*	V-MOS, Sw, 60V, ±0,2A, <10e(10mA)	35a	Nec	BSS84, 2SJ185
2SJ211	MOS-P-FET-e*	V-MOS, Sw, 100V, ±0,2A, <20e(10mA)	35a	Nec	-
2SJ212	MOS-P-FET-e*	V-MOS, Sw, 60V, ±0,5A, <3Ω(0,5A)	39b	Nec	2SJ199, 2SJ213
2SJ213	MOS-P-FET-e*	V-MOS, Sw, 100V, ±0,5A, <4,2Ω(0,5A)	39b	Nec	2SJ199
2SJ214(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 40W, <0,18Ω(5A)	30c$	Hit	2SJ219, 2SJ296
2SJ215	MOS-P-FET-e*	V-MOS, LogL, 60V, 35A, 125W, <0,06Ω	18c$	Hit	2SJ217
2SJ216	MOS-P-FET-e*	=2SJ215: Iso, 50W	?18c	Hit	2SJ218
2SJ217	MOS-P-FET-e*	V-MOS, LogL, 60V, 45A, 150W, <0,042©	18c$	Hit	-
2SJ218	MOS-P-FET-e*	=2SJ217: Iso, 60W	?18c	Hit	-
2SJ219(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,11Ω(5A)	30c$	Hit	2SJ268, 2SJ296, 2SJ384
2SJ22	P-FET	AF, LN, 80V, Idss=0,3..0,7mA	2d	Son	-
2SJ220(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 75W, <0,085Ω(10A)	30c$	Hit	2SJ241, 2SJ297, 2SJ401, 2SJ409
2SJ221	MOS-P-FET-e*	V-MOS, LogL, 100V, 20A, 75W	17c$	Hit	-
2SJ222	MOS-P-FET-e*	=2SJ221: Iso, 35W	17c	Hit	-
2SJ223(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 10W, <0,7Ω(5A)	30c$	Hit	2SJ326
2SJ224	MOS-P-FET-e	V-MOS, 60V, 12A, 80W, <0,2Ω(5A)	30c$	Tos	2SJ219, 2SJ296
2SJ225	MOS-P-FET-e	V-MOS, Sw, 30V, 1A, 1W, <0,75Ω(0,5A)	9c	Sanyo	2SJ196
2SJ226	MOS-P-FET-e*	V-MOS, Sw, 30V, 2A, 1,5W, <0,3Ω(5A)	?12b	Sanyo	-
2SJ227	MOS-P-FET-e*	V-MOS, Sw, 30V, 3A, 1,5W, <0,13Ω(1,5A)	?12b	Sanyo	-
2SJ228	MOS-P-FET-e*	V-MOS, LogL, 60V, 0,8A, 1W, <1,2Ω(0,5A)	9c	Sanyo	2SJ353
2SJ229	MOS-P-FET-e*	V-MOS, LogL, 60V, 1,6A, <0,45Ω(0,8W)	?12b	Sanyo	-
2SJ230	MOS-P-FET-e*	V-MOS, LogL, 60V, 2,5A, <0,21Ω(1,5A)	?12b	Sanyo	-
2SJ231	MOS-P-FET-e*	V-MOS, Sw, 100V, 0,5A, 1W, <2,4Ω(0,25A)	9c	Sanyo	-
2SJ232	MOS-P-FET-e*	V-MOS, LogL, 100V, 1,2A, <0,95Ω(0,5A)	?12b	Sanyo	-
2SJ233	MOS-P-FET-e*	V-MOS, LogL, 100V, 1,8A, <0,4Ω(5A)	?12b	Sanyo	-
2SJ234(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 2,5A, 10W, <0,4Ω(1,5A)	30c$	Hit	2SJ191
2SJ235(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 3A, 20W, <0,4e(2A), integr. Rgate	30c$	Hit	(2SJ182)
2SJ236	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,18Ω(5A), integr. Rgate	17c	Hit	(2SJ176)
2SJ237	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,11Ω(8A), integr. Rgate	17c	Hit	(2SJ177, 2SJ293)
2SJ238	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, <0,85Ω(0,5A)	39b	Tos	2SJ190, 2SJ193, 2SJ278
2SJ239	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,25Ω(2,5A)	30c$	Tos	2SJ183, 2SJ192, 2SJ195, 2SJ279
2SJ240	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 45W, <0,045Ω(10A)	17c	Tos	2SJ177, 2SJ294, 2SJ322, 2SJ330
2SJ241	MOS-P-FET-e	=2SJ240: 100W	30c$	Tos	2SJ220, 2SJ297, 2SJ401, 2SJ409
2SJ243	MOS-P-FET-e*	V-MOS, Sw, 30V, ±0,1A, <25Ω(10mA)	35(1,6mm)	Nec	-
2SJ244	MOS-P-FET-e*	V-MOS, LogL, 12V, 2A, <0,9Ω(0,5A), integr. Rgate	39b	Hit	(2SJ317)
2SJ245(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,25Ω(5A)	30c$	Hit	2SJ192, 2SJ279
2SJ246(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 7A, 20W, <0,17Ω(5A)	30c$	Hit	2SJ333
2SJ247	MOS-P-FET-e*	V-MOS, LogL, 100V, 8A, 40W, <0,3Ω(5A)	17c$	Hit	-
2SJ248	MOS-P-FET-e*	=2SJ247: Iso, 25W	17c	Hit	2SJ350
2SJ249	MOS-P-FET-e	V-MOS, Pow, 100V, 15A, 45W, <0,16Ω(5A)	17c	Tos	2SJ142, 2SJ222
2SJ250	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 12W, <0,19Ω(5A)	14b	Hit	-
2SJ251	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 50W, <0,17Ω(5A)	17c$	Sanyo	2SJ172
2SJ252	MOS-P-FET-e*	V-MOS, LogL, 30V, 12A, 60W, <0,13Ω(5A)	17c$	Sanyo	2SJ173, 2SJ290

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2SJ253	MOS-P-FET-e*	V-MOS, LogL, 30V, 20A, 70W, <75mΩ(10A)	17c$	Sanyo	2SJ174, 2SJ291
2SJ254	MOS-P-FET-e*	V-MOS, LogL, 30V, 8A, 25W, <0,12Ω(5A)	17c	Sanyo	2SJ175, 2SJ236
2SJ255	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 25W, <95mΩ(5A)	17c	Sanyo	2SJ175, 2SJ236
2SJ256	MOS-P-FET-e*	V-MOS, LogL, 30V, 18A, 30W, <55mΩ(10A)	17c	Sanyo	2SJ177, 2SJ294, 2SJ374
2SJ257	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 50W, <0,12Ω(5A)	30c$	Sanyo	2SJ214
2SJ258	MOS-P-FET-e*	V-MOS, LogL, 30V, 12A, 60W, <95mΩ(5A)	30c$	Sanyo	2SJ214
2SJ259	MOS-P-FET-e*	V-MOS, LogL, 30V, 20A, 70W, <55mΩ(10A)	30c$	Sanyo	2SJ409
2SJ260	MOS-P-FET-e*	V-MOS, LogL, 60V, 8A, 50W, <0,27Ω(5A)	17c$	Sanyo	2SJ172
2SJ261	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 60W, <0,2Ω(5A)	17c$	Sanyo	2SJ172
2SJ262	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 70W, <0,11Ω(5A)	17c$	Sanyo	2SJ174, 2SJ291
2SJ263	MOS-P-FET-e*	V-MOS, LogL, 60V, 6A, 25W, <0,2Ω(5A)	17c	Sanyo	2SJ175, 2SJ236
2SJ264	MOS-P-FET-e*	V-MOS, LogL, 60V, 8A, 25W, <0,15Ω(5A)	17c	Sanyo	2SJ175, 2SJ236
2SJ265	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,11Ω(5A)	17c	Sanyo	2SJ176, 2SJ293
2SJ266	MOS-P-FET-e*	V-MOS, LogL, 60V, 8A, 50W, <0,2Ω(5A)	30c$	Sanyo	2SJ214
2SJ267	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 60W, <0,15Ω(5A)	30c$	Sanyo	2SJ214
2SJ268	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 70W, <0,08Ω(5A)	30c$	Sanyo	2SJ220, 2SJ241, 2SJ297, 2SJ401
2SJ269	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 50W, <0,55Ω(5A)	17c$	Sanyo	-
2SJ270	MOS-P-FET-e*	V-MOS, LogL, 100V, 8A, 60W, <0,4Ω(5A)	17c$	Sanyo	2SJ247
2SJ271	MOS-P-FET-e*	V-MOS, LogL, 100V, 15A, 70W, <0,22Ω(5A)	17c$	Sanyo	2SJ221
2SJ272	MOS-P-FET-e*	V-MOS, LogL, 100V, 4A, 25W, <0,4Ω(5A)	17c	Sanyo	2SJ248
2SJ273	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 25W, <0,3Ω(5A)	17c	Sanyo	2SJ248
2SJ274	MOS-P-FET-e*	V-MOS, LogL, 100V, 12A, 30W, <0,16Ω(5A)	17c	Sanyo	2SJ222
2SJ275	MOS-P-FET-e*	V-MOS, LogL, 100V, 6A, 50W, <0,4Ω(5A)	30c$	Sanyo	-
2SJ276	MOS-P-FET-e*	V-MOS, LogL, 100V, 8A, 50W, <0,3Ω(5A)	30c$	Sanyo	-
2SJ277	MOS-P-FET-e*	V-MOS, LogL, 100V, 15A, 70W, <0,16Ω(5A)	30c$	Sanyo	2SJ409
2SJ278	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, <0,83Ω(0,5A)	39b	Hit	2SJ190, 2SJ197, 2SJ238, 2SJ450
2SJ279(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,2Ω(5A)	30c$	Hit	2SJ245
2SJ280(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <43mΩ(10A)	30c$	Hit	2SJ402,
2SJ281	MOS-P-FET-e	V-MOS, 250V, 3A, 30W, <2,6Ω	30c$	Sanyo	-
2SJ282	MOS-P-FET-e*	V-MOS, LogL, 250V, 3A, 50W, <2Ω(1,5A)	17c$	Sanyo	-
2SJ283	MOS-P-FET-e	V-MOS, 120V, 5A, 25W, <1,4Ω	17c	Tos	2SJ350
2SJ284	MOS-P-FET-e	V-MOS, LogL, 30V, 0,3A, <2,2Ω(0,15A)	35a	Sanyo	-
2SJ285	MOS-P-FET-e	V-MOS, LogL, 60V, 0,25A, <3Ω(0,15A)	35a	Sanyo	2SJ210..211
2SJ286	MOS-P-FET-e	V-MOS, LogL, 100V, 0,15A, <7Ω(0,5A)	35a	Sanyo	2SJ209, 2SJ211
2SJ287	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,5A, <2,2Ω(0,25A)	39b	Sanyo	2SJ190, 2SJ278
2SJ288	MOS-P-FET-e*	V-MOS, LogL, 60V, 0,5A, <3Ω(0,25A)	39b	Sanyo	2SJ190, 2SJ278
2SJ289	MOS-P-FET-e*	V-MOS, LogL, 100V, 0,5A, <7,5Ω	39b	Sanyo	2SJ193
2SJ29	P-FET	V-FET-Pow, 140V, 10A, 100W, 15Ω	23a$	Hit	-
2SJ290	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <95mΩ(5A)	17c$	Hit	2SJ173, 2SJ541, 2SJ542
2SJ291	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 60W, <65mΩ(10A)	17c$	Hit	2SJ174, 2SJ221, 2SJ543
2SJ292	MOS-P-FET-e*	=2SJ280:	17c$	Hit	2SJ543
2SJ293	MOS-P-FET-e*	=2SJ290: Iso, 30W	17c	Hit	2SJ176, 2SJ321
2SJ294	MOS-P-FET-e*	=2SJ291: Iso, 35W	17c	Hit	2SJ177, 2SJ240, 2SJ330, 2SJ374
2SJ295	MOS-P-FET-e*	=2SJ280: Iso, 35W	17c	Hit	2SJ323
2SJ296(L,S)	MOS-P-FET-e*	=2SJ290:	30c$	Hit	2SJ219, 2SJ268, 2SJ384
2SJ297(L,S)	MOS-P-FET-e*	=2SJ291:	30c$	Hit	2SJ220, 2SJ241, 2SJ401, 2SJ409
2SJ298	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 12W, <0,12Ω(5A)	14b	Hit	2SJ250
2SJ299	MOS-P-FET-e*	=2SJ298:	30c$	Hit	2SJ245, 2SJ279, 2SJ318
2SJ300	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 12W, <0,08Ω(5A)	14c$	Hit	2SJ250
2SJ302	MOS-P-FET-e*	V-MOS, 60V, 16A, 75W, <0,1Ω(5A)	17c$	Nec	2SJ173, 2SJ290, 2SJ328
2SJ302Z	MOS-P-FET-e*	=2SJ302:	30c$	-	2SJ241, 2SJ268, 2SJ297, 2SJ384..
2SJ303	MOS-P-FET-e*	V-MOS, LogL, 60V, 14A, 35W, <0,1Ω(5A)	17c	Nec	2SJ237, 2SJ275, 2SJ293, 2SJ329
2SJ304	MOS-P-FET-e*	V-MOS, LogL, 60V, 14A, 40W, <0,12Ω(5A)	17c	Tos	2SJ176, 2SJ265, 2SJ303, 2SJ329
2SJ305	MOS-P-FET-e*	V-MOS, 30V, 0,2A, <4Ω(0,05A)	35a	Sanyo	2SJ210..211
2SJ306	MOS-P-FET-e*	V-MOS, 250V, 3A, 25W, <2Ω(1,5A)	17c	Sanyo	2SJ307
2SJ307	MOS-P-FET-e*	V-MOS, 250V, 6A, 30W, <3Ω(5A)	17c	Sanyo	2SJ308, 2SJ320
2SJ308	MOS-P-FET-e*	V-MOS, 250V, 9A, 40W, <0,48Ω(5A)	17c	Sanyo	-
2SJ312	MOS-P-FET-e	=2SJ304:	30c$	Tos	2SJ268
2SJ313	MOS-P-FET-e	V-MOS, 180V, 1A, 25W	17c	Tos	-
2SJ314-01(L,S)	MOS-P-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,48Ω(2,5A)	30c$	Fjd	2SJ192, 2SJ245, 2SJ279, 2SJ327
2SJ315	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,25Ω(2,5A)	30c$	Tos	2SJ192, 2SJ245, 2SJ279, 2SJ327
2SJ316	MOS-P-FET-e*	V-MOS, LogL, 12V, 1A, <0,42Ω(0,5A)	39b	Tos	2SJ190, 2SJ278
2SJ317	MOS-P-FET-e*	V-MOS, LogL, 12V, ±2A, <0,7e(0,5A), integr. Rgate	39b	Hit	(2SJ244)
2SJ318(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 20W, <0,13Ω(5A)	30c$	Hit	2SJ245, 2SJ279, 2SJ299

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2SJ319(L,S)	MOS-P-FET-e*	V-MOS, 200V, 3A, 20W, <2,3Ω(5A)	30c$	Hit	-
2SJ32	P-FET	AF, Sw, 150V, 0,6W, 350e	-	Shi	-
2SJ320	MOS-P-FET-e*	V-MOS, LogL, 250V, 4A, 25W, <1,3Ω(5A)	17c	Sanyo	-
2SJ321	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <95mΩ(5A)	17c	Hit	2SJ176, 2SJ293
2SJ322	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <65mΩ(10A)	17c	Hit	2SJ177, 2SJ294
2SJ323	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 35W, <43mΩ(10A)	17c	Hit	2SJ295
2SJ324(Z)	MOS-P-FET-e*	V-MOS, LogL, 30V, ±2A, 20W, <0,25Ω(5A)	30c$	Nec	2SJ191, 2SJ326
2SJ325(Z)	MOS-P-FET-e*	V-MOS, LogL, 30V, ±4A, 20W, <0,11Ω(5A)	30c$	Nec	2SJ245, 2SJ327, 2SJ327
2SJ326(Z)	MOS-P-FET-e*	V-MOS, LogL, 60V, ±2A, 20W, <0,37Ω(5A)	30c$	Nec	2SJ191, 2SJ194
2SJ327(Z)	MOS-P-FET-e*	V-MOS, LogL, 60V, ±4A, 20W, <0,17Ω(5A)	30c$	Nec	2SJ192, 2SJ195, 2SJ245, 2SJ279
2SJ328	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 75W, <65mΩ(10A)	17c$	Nec	2SJ174, 2SJ221
2SJ328Z	MOS-P-FET-e*	=2SJ328:	30c$	-	2SJ241, 2SJ409
2SJ329	MOS-P-FET-e*	V-MOS, LogL, 60V, ±15A, 35W, <0,06Ω(5A)	17c	Nec	2SJ176, 2SJ265, 2SJ293
2SJ33	P-FET	=2SJ32: 200V	-	Shi	-
2SJ330	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 35W, <50mΩ(10A)	17c	Nec	2SJ177, 2SJ294, 2SJ322, 2SJ374
2SJ331	MOS-P-FET-e*	V-MOS, LogL, 60V, ±30A, 150W, <0,03Ω	18c$	Nec	2SJ217
2SJ332(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 20W, <0,08Ω(5A)	30c$	Hit	2SJ389
2SJ333(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 7A, 20W, <0,14Ω(5A)	30c$	Hit	2SJ246
2SJ334	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 45W, <38mΩ(10A)	17c	Tos	2SJ295, 2SJ323
2SJ335	MOS-P-FET-e*	V-MOS, LogL, 12V, 0,5A, <1.4Ω	39b	Sanyo	2SJ190, 2SJ278
2SJ336	MOS-P-FET-e*	V-MOS, LogL, 12V, 2A, 20W, <0,35Ω(5A)	30c$	Sanyo	2SJ191
2SJ337	MOS-P-FET-e*	V-MOS, LogL, 12V, 8A, 30W, <0,09e(5A)	30c$	Sanyo	2SJ246, 2SJ333
2SJ338	MOS-P-FET-e*	V-MOS, 180V, 1A, 20W, <5Ω(0,5A)	30c$	Tos	2SJ130
2SJ339	MOS-P-FET-e*	V-MOS, LogL, 60V, 25A, 40W, <55mΩ(10A)	17c	Sanyo	2SJ295, 2SJ323
2SJ340	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(10A)	30c$	Sanyo	2SJ280
2SJ341	MOS-P-FET-e*	V-MOS, LogL, 20V, 5A, 12W, <0,12Ω(5A)	14b	Hit	2SJ250, 2SJ300
2SJ342	MOS-P-FET-e*	V-MOS, int.Di (G>S), 50V, 0,05A, <50Ω	41f	Tos	-
2SJ343	MOS-P-FET-e*	-	35	Tos	→2SJ343
2SJ344	MOS-P-FET-e*	-	35(2mm)	Tos	→2SJ344
2SJ345	MOS-P-FET-e	V-MOS, int.Di (G>S), 20V, 0,05A, <40Ω	35a	Tos	-
2SJ346	MOS-P-FET-e*	-	35(2mm)	Tos	→2SJ346
2SJ347	MOS-P-FET-e*	-	35(1,6mm)	Tos	→2SJ347
2SJ348	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 70W, <55mΩ(10A)	17c$	Sanyo	2SJ292
2SJ349	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <45mΩ(10A)	17c	Tos	2SJ177, 2SJ294, 2SJ322, 2SJ374
2SJ350	MOS-P-FET-e*	V-MOS, LogL, 120V, 6A, 20W, <0,7Ω(5A)	17c	Hit	-
2SJ351	MOS-P-FET-e*	V-MOS, AF-Pow, 180V, 8A, 100W, 320/120nS	18d*	Hit	-
2SJ352	MOS-P-FET-e*	=2SJ351: 200V	18d*	Hit	-
2SJ353	MOS-P-FET-e*	V-MOS, LogL, 60V, ±1,5A, 1W, <0,37Ω(5A)	9c	Nec	-
2SJ355	MOS-P-FET-e*	V-MOS, LogL, 30V, ±2A, <0,35Ω(5A)	39b	Nec	2SJ356
2SJ356	MOS-P-FET-e*	V-MOS, LogL, 60V, ±2A, <0,5Ω(5A)	39b	Nec	2SJ518
2SJ357	MOS-P-FET-e*	V-MOS, LogL, 30V, ±3A, <0,2Ω(1,5A)	39b	Nec	2SJ358
2SJ358	MOS-P-FET-e*	V-MOS, LogL, 60V, ±3A, <0,3Ω(1,5A)	39b	Nec	-
2SJ359	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, <0,25Ω(2,5A)	?12c	Tos	-
2SJ360	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, <0,73Ω(0,5A)	39b	Tos	2SJ190, 2SJ238, 2SJ278, 2SJ450
2SJ361	MOS-P-FET-e*	V-MOS, LogL, 20V, 2A, <0,4Ω(1A), integr. Rgate	39b	Hit	-
2SJ362	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 20W, <0,65Ω(5A)	30c$	Sanyo	2SJ191, 2SJ194
2SJ363	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, <0,45Ω(1A), integr. Rgate	39b	Hit	(2SJ355..356)
2SJ364	P-FET	-	35(2mm)	Mat	→2SJ364
2SJ364-O	P-FET	-	35(2mm)	Mat	→2SJ364
2SJ364-P	P-FET	-	35(2mm)	Mat	→2SJ364
2SJ364-Q	P-FET	-	35(2mm)	Mat	→2SJ364
2SJ364-R	P-FET	-	35(2mm)	Mat	→2SJ364
2SJ365	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, 20W, <0,45Ω(5A)	30c$	Shi	2SJ191, 2SJ223, 2SJ326
2SJ366	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 25W, <0,25Ω(2,5A)	30c$	Shi	2SJ192, 2SJ245, 2SJ279, 2SJ327, 2SJ377
2SJ367	MOS-P-FET-e*	=2SJ366: 40W	30c$	Shi	2SJ275
2SJ368	MOS-P-FET-e*	=2SJ367: 30W	17c	Shi	2SJ248, 2SJ263, 2SJ350, 2SJ438
2SJ369	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 50W, <0,16Ω(5A)	30c$	Shi	2SJ214, 2SJ219, 2SJ268, 2SJ296
2SJ370	MOS-P-FET-e*	=2SJ369: 35W	17c	Shi	2SJ236, 2SJ293, 2SJ321, 2SJ390
2SJ371	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 60W, <0,1Ω(7,2A)	30c$	Shi	2SJ219, 2SJ268, 2SJ296, 2SJ384
2SJ372	MOS-P-FET-e*	=2SJ371: 40W	17c	Shi	2SJ237, 2SJ265, 2SJ293, 2SJ321, 2SJ329
2SJ373	MOS-P-FET-e*	V-MOS, 60V, 20A, 70W, <0,07Ω(10A)	30c$	Shi	2SJ220, 2SJ241, 2SJ297, 2SJ401
2SJ374	MOS-P-FET-e*	=2SJ373: 50W	17c	Shi	2SJ240, 2SJ294, 2SJ322, 2SJ330, 2SJ374
2SJ375	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <45mΩ(10A)	30c$	Shi	2SJ280, 2SJ402
2SJ376	MOS-P-FET-e*	=2SJ375: 55W	17c	Shi	2SJ295, 2SJ323, 2SJ334

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2SJ377	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,19Ω(2,5A)	30c$	Tos	2SJ192, 2SJ195, 2SJ245, 2SJ327
2SJ378	MOS-P-FET-e*	=2SJ377: 1,2W	?12c	Tos	-
2SJ379	MOS-P-FET-e*	V-MOS, LogL, 100V, 8A, 15W, <0,21Ω(5A)	?30c$	Tos	-
2SJ380	MOS-P-FET-e*	V-MOS, LogL, 100V, 12A, 35W, <0,21Ω(5A)	17c	Tos	2SJ222
2SJ381	MOS-P-FET-e*	V-MOS, LogL, 12V, 2A, <0,4Ω(5A)	39b	Sanyo	2SJ355..356
2SJ382	MOS-P-FET-e*	V-MOS, LogL, 12V, 4A, 20W, <177mΩ(5A)	30c$	Sanyo	2SJ192, 2SJ245, 2SJ327
2SJ383	MOS-P-FET-e*	V-MOS, LogL, 12V, 8A, 30W, <82mΩ(5A)	30c$	Sanyo	2SJ389
2SJ384(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,1Ω(5A)	30c$	Hit	2SJ219, 2SJ268, 2SJ296, 2SJ409
2SJ386	MOS-P-FET-e*	V-MOS, LogL, 30V, 3A, 0,9W, <0,4Ω(5A)	7c,b?(9mm)	Hit	-
2SJ387(L,S)	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 20W, <70mΩ(5A)	30c$	Hit	2SJ388..389
2SJ388(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 20W, <80mΩ(5A)	30c$	Hit	2SJ389
2SJ389(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <135mΩ(5A)	30c$	Hit	-
2SJ39	P-FET	Dual, 50V, Idss=1..12mA, Up<6V	7-SIP/bp	Mit	-
2SJ390	MOS-P FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,12Ω(5A)	17c	Hit	2SJ175..176, 2SJ236
2SJ399	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,2A, <7Ω(100mA), integr. Rgate	35a	Hit	-
2SJ40	P-FET	Sw, 50V, Idss=0,6..12mA, Up<6V	41a	Mit	-
2SJ400	MOS-P-FET-e*	V-MOS, LogL, 30V, 30A, 70W, <40mΩ(10A)	30c$	Sanyo	2SJ280, 2SJ402, 2SJ553, 2SJ505
2SJ401	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 100W, <45mΩ(10A)	30c$	Tos	2SJ220, 2SJ241, 2SJ297, 2SJ409
2SJ402	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 100W, <38mΩ(10A)	30c$	Tos	2SJ280, 2SJ553
2SJ403	MOS-P-FET-e*	V-MOS, LogL, 200V, 5A, 25W, <1,1Ω(2,5A)	17c	Sanyo	2SJ320
2SJ404	MOS-P-FET-e*	V-MOS, LogL, 200V, 6A, 25W, <0,8Ω(5A)	17c	Sanyo	-
2SJ405	MOS-P-FET-e*	V-MOS, LogL, 200V, 8A, 30W, <0,5Ω(5A)	17c	Sanyo	-
2SJ406	MOS-P-FET-e*	V-MOS, LogL, 200V, 12A, 40W, <0,23Ω	17c	Sanyo	-
2SJ407	MOS-P-FET-e*	V-MOS, 200V, 5A, 30W, <1Ω(2,5A)	17c	Tos	2SJ320, 2SJ403, 2SJ410
2SJ408(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 50A, 100W, <0,02Ω(20A)	30c$	Hit	-
2SJ409(L,S)	MOS-P-FET-e*	V-MOS, LogL, 100V, 20A, 75W, <0,16Ω(10A)	30c$	Hit	-
2SJ410(L,S)	MOS-P-FET-e*	V-MOS, 200V, 6A, 30W, <0,85Ω(5A)	17c	Hit	2SJ307, 2SJ405
2SJ411	MOS-P-FET-e*	V-MOS, LogL, 30V, ±5A, 1W, <0,11Ω(2,5A)	9c	Nec	(2SJ183, 2SJ192, 2SJ245, 2SK279, 2SJ327)
2SJ412	MOS-P-FET-e*	V-MOS, LogL, 100V, 16A, 60W, <0,21Ω(5A)	30c$	Tos	IRF9540S, 2SJ277
2SJ413	MOS-P-FET-e*	V-MOS, LogL, 60V, 50A, 70W, <0,03Ω	18c	Sanyo	2SJ218
2SJ414	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,08Ω(5A)	-	Sanyo	-
2SJ415	MOS-P-FET-e*	V-MOS, LogL, 60V, 8A, 40W, <0,15Ω(5A)	-	Sanyo	-
2SJ416	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, <0,44Ω(5A)	39b	Sanyo	2SJ356, 2SJ518, 2SJ563
2SJ417	MOS-P-FET-e*	V-MOS, LogL, 30V, 4A, 20W, <0,29Ω	30c$	Sanyo	2SJ192, 2SJ245, 2SJ279, 2SJ327
2SJ418	MOS-P-FET-e*	V-MOS, LogL, 30V, 8A, 30W, <145mΩ	30c$	Sanyo	-
2SJ419	MOS-P-FET-e*	V-MOS, LogL, 12V, 4A, <82mΩ(5A)	8-MDIP	Sanyo	-
2SJ420	MOS-P-FET-e*	V-MOS, LogL, 12V, 5A, <63mΩ(5A)	8-MDIP	Sanyo	-
2SJ421	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, <107mΩ(5A)	8-MDIP	Sanyo	-
2SJ424	MOS-P-FET-e	V-MOS, 60V, ±5A, 25W, <0,5Ω(2,5A)	17c	Sak	2SJ135, 2SJ154, 2SJ158, 2SJ272
2SJ425	MOS-P-FET-e	V-MOS, 60V, ±8A, 30W, <0,28Ω(5A)	17c	Sak	2SJ137, 2SJ147, 2SJ175, 2SJ236, 2SJ390
2SJ426	MOS-P-FET-e	V-MOS, 60V, ±15A, 35W, <0,14Ω(5A)	17c	Sak	2SJ141, 2SJ143, 2SJ265, 2SJ321, 2SJ329..
2SJ43	P-FET	GenP, 50V, Idss=0,5..12mA, Up<3V	7a	Mat	2SJ129
2SJ437	MOS-P-FET-e	V-MOS, 30V, 35A, 50W, <30mΩ(10A)	-	Sanyo	-
2SJ438	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 25W, <0,19Ω(2,5A)	17c	Tos	2SJ263, 2SJ272, 2SJ274
2SJ439	MOS-P-FET-e*	V-MOS, LogL, 16V, 5A, 20W, <0,2Ω(2,5A)	30c$	Tos	2SJ183, 2SJ192, 2SJ239
2SJ44	P-FET	GenP, LN, 40V, Idss=1..18mA, Up<1,5V	7a	Nec	2N5021, 2SJ74
2SJ440	MOS-P-FET-e*	V-MOS, 180V, 9A, 80W	16c	Tos	-
2SJ443	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,18Ω(5A)	17c	Hit	2SJ175..176, 2SJ236, 2SJ390
2SJ448	MOS-P-FET-e*	V-MOS, 250V, ±4A, 30W, <2Ω(5A)	17c	Nec	2SJ320, 2SJS12
2SJ449	MOS-P-FET-e*	V-MOS, 250V, ±6A, 35W, <0,8Ω(5A)	17c	Nec	2SJ307..308
2SJ45	P-FET	GenP, LN, 40V, Idss=1..18mA, Up<1,5V	7a	Nec	2N5021, 2SJ74
2SJ450	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, <1,2Ω(0,5A)	39b	Hit	2SJ190, 2SJ197, 2SJ238, 2SJ278
2SJ451	MOS-P-FET-e*	V-MOS, LogL, 20V, 0,2A, <3,5Ω(0,1A), integr. Rgate	35a	Hit	-
2SJ452	MOS-P-FET-e*	V-MOS, LogL, 50V, 0,2A, <7Ω(0,1A), integr. Rgate	35a	Hit	-
2SJ453	MOS-P-FET-e*	V-MOS, 250V, 3A, 30W, <2,6Ω(1,5A)	30c$	Sanyo	2SJ281
2SJ454	MOS-P-FET-e*	FREDFET, 250V, 5A, 40W, <1,3Ω(5A)	-	Sanyo	-
2SJ455	MOS-P-FET-e*	FREDFET, 250V, 7A, 45W, <0,9Ω(5A)	-	Sanyo	-
2SJ456	MOS-P-FET-e*	FREDFET, 250V, 9A, 50W, <0,62Ω(5A)	-	Sanyo	-
2SJ457	MOS-P-FET-e	FREDFET, 450V, 0,5A, 30W, <15Ω(0,5A)	30c$	Sanyo	-
2SJ458	MOS-P-FET-e	FREDFET, 450V, 2A, 60W, <5,5Ω(5A)	30c$	Sanyo	-
2SJ459	MOS-P-FET-e	FREDFET, 450V, 4A, 70W, <2,8Ω(5A)	30c$	Sanyo	-
2SJ460	MOS-P-FET-e*	V-MOS, LogL, 50V, ±0,1A, <0,05Ω(30A)	9c	Nec	BSS110, 2SJ148, 2SJ184
2SJ461	MOS-P-FET-e*	-	35	Nec	→2SJ461
2SJ462	MOS-P-FET-e*	V-MOS, LogL, 12V, ±2,5A, <0,19Ω	39b	Nec	2SJ356, 2SJ358

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2SJ463	MOS-P-FET-e*	V-MOS, LogL, 30V, ±0,1A, <60Ω(10A)	35(2mm)	Nec	-
2SJ463A	MOS-P-FET-e*	-	35(2mm)	Nec	→2SJ463A
2SJ464	MOS-P-FET-e*	V-MOS, LogL, 100V, 18A, 45W, <0,12Ω(5A)	17c	Tos	-
2SJ465	MOS-P-FET-e*	V-MOS, LogL, 16V, 2A, <0,71Ω(5A)	39b	Tos	2SJ517, 2SJ562, 2SJ563
2SJ466	MOS-P-FET-e*	V-MOS, LogL, 30V, 35A, 50W, <0,03Ω(10A)	-	Sanyo	-
2SJ467	MOS-P-FET-e*	V-MOS, LogL, 30V, 8A, 30W, <0,1Ω(5A)	30c$	Sanyo	2SJ418
2SJ468	MOS-P-FET-e*	V-MOS, LogL, 30V, 4A, <0,1Ω(5A)	8-MDIP	Sanyo	-
2SJ469	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, <0,08Ω(5A)	8-MDIP	Sanyo	-
2SJ47	MOS-P-FET-e	V-MOS, 100V, 7A, 100W, 25/24nS, <1,7Ω	23e*	Hit	2SJ55..56, 2SJ160..162
2SJ471	MOS-P-FET-e*	V-MOS, LogL, 30V, 30A, 30W, <35mΩ(10A)	17c	Hit	2SJ295, 2SJ323
2SJ472-01(L,S)	MOS-P-FET-e	V-MOS, LogL, 30V, 5A, 15W, <0,85Ω	30c$	Fjd	2SJ183, 2SJ192, 2SK239, 2SJ245, 2SJ377
2SJ473-01(L,S)	MOS-P-FET-e	V-MOS, LogL, 60V, 7A, 20W, <0,35Ω	30c$	Fjd	-
2SJ474-01(L,S)	MOS-P-FET-e	V-MOS, LogL, 60V, 7A, 20W, <0,35Ω	30c$	Fjd	2SJ266
2SJ475-01	MOS-P-FET-e	V-MOS, LogL, 60V, 25A, 50W, <0,11Ω	17c$	Fjd	2SJ174, 2SJ221, 2SJ291..92, 2SJ328
2SJ476-01	MOS-P-FET-e	V-MOS, LogL, 60V, 25A, 50W, <0,11Ω	30c$	Fjd	2SJ220, 2SJ241, 2SJ297, 2SJ401, 2SJ409
2SJ477-01	MOS-P-FET-e	V-MOS, LogL, 60V, 25A, 40W, <0,11Ω	17c$	Fjd	2SJ174, 2SJ221, 2SJ291..92, 2SJ328
2SJ478	MOS-P-FET-e	V-MOS, LogL, 60V, 20A, 80W, <45mΩ(10A)	17c$	Sanyo	2SJ174, 2SJ221, 2SJ291, 2SJ328
2SJ479(L,S)	MOS-P-FET-e*	=2SJ471:50W	30c$	Hit	-
2SJ48	MOS-P-FET-e	=2SJ47:120V	23e*	Hit	2SJ55..56, 2SJ160..162
2SJ480	MOS-P-FET-e	V-MOS, LogL, 12V, 0,3A, <1,4e	35	Sanyo	-
2SJ481	MOS-P-FET-e	V-MOS, LogL, 30V, 2A, <0,49Ω	39b	Sanyo	2SJ356
2SJ483	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, 0,9W, <0,11Ω(2,5A)	7c(9mm)	Hit	-
2SJ484	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, <0,23Ω(5A)	39b	Hit	2SJ356
2SJ485	MOS-P-FET-e*	V-MOS, LogL, 60V, 4A, 20W, <0,48Ω(5A)	30c$	Sanyo	2SJ192, 2SJ239, 2SJ279, 2SJ327..
2SJ486	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,3A, <0,65Ω, integr. Rgate	35a	Hit	-
2SJ487	MOS-P-FET-e*	V-MOS, LogL, 30V, 3A, 10W, <0,5Ω	30c$	Shi	2SJ182, 2SJ235
2SJ488	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, 15W, <0,3Ω	30c$	Shi	2SJ183, 2SJ239, 2SJ279, 2SJ377
2SJ489	MOS-P-FET-e*	V-MOS, LogL, 30V, 7A, 20W, <0,21Ω	30c$	Shi	2SJ389
2SJ49	MOS-P-FET-e	=2SJ47:140V	23e*	Hit	2SJ55..56, 2SJ161..162
2SJ490	MOS-P-FET-e*	V-MOS, LogL, 30V, 20A, 50W, <0,12Ω	30c$	Shi	MTD20P06HDL
2SJ491	MOS-P-FET-e*	V-MOS, LogL, 30V, 20A, 55W, <60mΩ	30c$	Shi	2SJ241, 2SJ297, 2SJ401, 2SJ552
2SJ492	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 70W, <185mΩ	17c$	Nec	2SJ174, 2SJ291, 2SJ328, 2SJ543
2SJ492-S,-ZJ	MOS-P-FET-e*	=2SJ492:	30c$	-	2SJ220, 2SJ241, 2SJ297, 2SJ401, 2SJ409
2SJ493	MOS-P-FET-e*	V-MOS, LogL, 60V, ±16A, 30W, <185mΩ	17c	Nec	2SJ303, 2SJ321, 2SJ329, 2SJ531, 2SJ534
2SJ494	MOS-P-FET-e*	V-MOS, LogL, 60V, ±20A, 35W, <61mΩ	17c	Nec	2SJ240, 2SJ294, 2SJ322, 2SJ330, 2SJ374
2SJ495	MOS-P-FET-e*	V-MOS, LogL, 60V, ±30A, 35W, <56mΩ	17c	Nec	2SJ295, 2SJ334, 2SJ504, 2SJ533, 2SJ535
2SJ496	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 0,9W, <0,24Ω(2,5A)	7c(9mm)	Hit	-
2SJ497	P-FET	Sw, 50V, 0,1A, Idss<0,1mA	35	Mat	-
2SJ498	P-FET	Sw, 50V, Idss=1..12mA, Up<6V	41	Mit	-
2SJ499	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 30W, <45mΩ(5A)	30c$	Sanyo	2SJ389, 2SJ529
2SJ50	MOS-P-FET-e	=2SJ47:160V	23e*	Hit	2SJ55..56, 2SJ162
2SJ501	MOS-P-FET-e*	V-MOS, LogL, 20V, 0,5A, <1Ω(0,0(A)	35a	Sanyo	BSH202, BSH203
2SJ502	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,5A, <0,6Ω(0,5A)	35	Sanyo	BSH202, BSH203
2SJ503	MOS-P-FET-e*	V-MOS, LogL, 30V, 4A, 20W, <0,18Ω(5A)	30c$	Sanyo	2SJ183, 2SJ192, 2SJ239, 2SJ279, 2SJ327..
2SJ504	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 30W, <95mΩ(10A)	17c	Hit	2SJ177, 2SJ294, 2SJ322, 2SJ330, 2SJ374
2SJ505(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 50A, 75W, <36mΩ(20A)	30c$	Hit	-
2SJ506(L,S)	MOS-P-FET-e*	V-MOS, LogL, 30V, 10A, 20W, <0,18Ω(5A)	30c$	Hit	2SJ389
2SJ507	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, 0,9W, <1Ω(0,5A)	7c(9mm)	Tos	2SJ353
2SJ508	MOS-P-FET-e*	-	39	Tos	→2SJ508
2SJ509	MOS-P-FET-e*	V-MOS, LogL, 100V, 1A, 0,9W, <2,5Ω(0,5A)	7c(9mm)	Tos	-
2SJ51	P-FET	AF, Sw, LN, 40V, Idss=6..50mA, Up<1,1V	7a(9mm)	Hit	2SJ70
2SJ511	MOS-P-FET-e*	V-MOS, 30V, 2A, <0,76Ω(5A)	39b	Tos	2SJ563, 2SJ416
2SJ512	MOS-P-FET-e*	V-MOS, 250V, 5A, 30W, <1,25Ω(2,5A)	17c	Tos	2SJ307, 2SJ449
2SJ516	MOS-P-FET-e*	V-MOS, 250V, 6,5A, 35W, <0,8Ω(5A)	17c	Tos	2SJ307, 2SJ308, 2SJ449
2SJ517	MOS-P-FET-e*	V-MOS, LogL, 20V, 2A, <0,24Ω(5A)	39b	Hit	2SJ562, 2SJ563
2SJ518	MOS-P-FET-e*	V-MOS, LogL, 60V, 2A, <0,63Ω(5A)	39b	Hit	2SJ356
2SJ519	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <40mΩ(10A)	17c	Sanyo	2SJ177, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ520	MOS-P-FET-e*	V-MOS, LogL, 20V, 10A, 20W, <0,1Ω(5A)	30c$	Sanyo	2SJ389, 2SJ529
2SJ522	MOS-P-FET-e	V-MOS, 400V, 5A, 70W, <2Ω(2,5A)	30c$	Sanyo	2SJ459
2SJ525	MOS-P-FET-e*	V-MOS, LogL, 30V, 5A, 1,3W, <0,2Ω(2,5A)	12c	Tos	(2SJ192, 2SJ239, 2SK279, 2SJ327, 2SK377)
2SJ526	MOS-P-FET-e*	V-MOS, LogL, 60V, 12A, 25W, <0,23Ω(5A)	17c	Hit	2SJ147, 2SJ237, 2SJ293, 2SJ303, 2SJ329
2SJ527(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,8Ω(5A)	30c$	Hit	2SJ183, 2SJ192, 2SJ239, 2SJ279..
2SJ528(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 7A, 20W, <0,34Ω(5A)	30c$	Hit	2SJ389
2SJ529(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 20W, <0,24Ω(5A)	30c$	Hit	2SJ389

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2SJ530(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,16Ω(5A)	30c$	Hit	MTD20P06HDL
2SJ531	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 30W, <0,11Ω(5A)	17c	Hit	2SJ177, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ532	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 30W, <95mΩ(10A)	17c	Hit	2SJ177, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ533	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 35W, <55mΩ(10A)	17c	Hit	2SJ295, 2SJ334, 2SJ504
2SJ534	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 30W, <0,11Ω(5A)	17c	Hit	2SJ177, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ535	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 35W, <55mΩ(10A)	17c	Hit	2SJ295, 2SJ334, 2SJ504
2SJ537	MOS-P-FET-e*	V-MOS, LogL, 50V, 5A, 0,9W, <0,34Ω(1,5A)	7c(9mm)	Tos	2SJ496
2SJ538	MOS-P-FET-e*	V-MOS, LogL, 30V, 15A, 30W, <0,03Ω(5A)	30c$	Sanyo	2SJ530
2SJ539	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 40W, <0,36Ω(5A)	17c$	Hit	2SJ172, 2SJ540
2SJ540	MOS-P-FET-e*	V-MOS, LogL, 60V, 12A, 50W, <0,23Ω(5A)	17c$	Hit	2SJ173, 2SJ290, 2SJ541, 2SJ542
2SJ541	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <155mΩ(5A)	17c$	Hit	2SJ173, 2SJ290, 2SJ542
2SJ542	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 60W, <110mΩ(5A)	17c$	Hit	2SJ174, 2SJ291, 2SJ543
2SJ543	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 75W, <95mΩ(10A)	17c$	Hit	2SJ174, 2SJ221, 2SJ291, 2SK328
2SJ544	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <55mΩ(10A)	17c$	Hit	2SJ292
2SJ545	MOS-P-FET-e*	V-MOS, LogL, 60V, 12A, 25W, <0,23Ω(5A)	17c	Hit	2SJ147, 2SJ237, 2SJ293, 2SJ303, 2SJ329
2SJ546	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <155mΩ(5A)	17c	Hit	2SJ176, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ547	MOS-P-FET-e*	V-MOS, LogL, 60V, 10A, 20W, <0,36Ω(5A)	17c	Hit	2SJ147, 2SJ175, 2SJ236, 2SJ390
2SJ548	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <155mΩ(5A)	17c	Hit	2SJ176, 2SJ240, 2SJ294, 2SJ330, 2SJ374
2SJ549(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 12A, 50W, <0,23Ω(5A)	30c$	Hit	2SJ219, 2SJ268, 2SJ296, 2SJ384
2SJ55	MOS-P-FET-e	V-MOS, 180V, 8A, 125W, <1,7Ω	23e*	Hit	-
2SJ550(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <155mΩ(5A)	30c$	Hit	2SJ219, 2SJ268, 2SJ296, 2SJ384
2SJ551(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 18A, 60W, <110mΩ(5A)	30c$	Hit	2SJ220, 2SJ241, 2SJ297, 2SJ401, 2SJ409
2SJ552(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 20A, 75W, <95mΩ(10A)	30c$	Hit	2SJ220, 2SJ241, 2SJ297, 2SJ401, 2SJ409
2SJ553(L,S)	MOS-P-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <55mΩ(10A)	30c$	Hit	2SJ280, 2SJ402, 2SJ553
2SJ554	MOS-P-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <55mΩ(20A)	18c$	Hit	2SJ217
2SJ555	MOS-P-FET-e*	V-MOS, LogL, 60V, 60A, 125W, <36mΩ(30A)	18c$	Hit	-
2SJ556	MOS-P-FET-e*	=2SJ554: Iso, 60W	?18c	Hit	2SJ218
2SJ557	MOS-P-FET-e*	V-MOS, LogL, 30V, ±2,5A, <0,29Ω	35a	Nec	-
2SJ559	MOS-P-FET-e*	V-MOS, LogL, 30V, ±0,1A, <60Ω	35a(1,6mm)	Nec	-
2SJ56	MOS-P-FET-e	=2SJ55: 200V	23e*	Hit	-
2SJ560	MOS-P-FET-e*	V-MOS, LogL, 20V, 1,5A, <1Ω	39b	Sanyo	2SJ517, 2SJ562, 2SJ563
2SJ561	MOS-P-FET-e*	V-MOS, LogL, 30V, 1,5A, <0,97Ω	39b	Sanyo	2SJ356, 2SJ518, 2SJ563
2SJ562	MOS-P-FET-e*	V-MOS, LogL, 20V, 2A, <0,48Ω	39b	Sanyo	2SJ356, 2SJ416, 2SJ517, 2SJ563
2SJ563	MOS-P-FET-e*	V-MOS, LogL, 30V, 2A, <0,55Ω	39b	Sanyo	2SJ356, 2SJ416, 2SJ518
2SJ569LS	MOS-P-FET-e*	V-MOS, LogL, 300V, 5A, 30W, <1,25Ω(5A)	17c	Sanyo	-
2SJ574	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,3A, <3,1Ω	35a	Hit	BSH201..203, 2SJ502
2SJ575	MOS-P-FET-e*	V-MOS, LogL, 30V, 0,1A, <7,9Ω	35a	Hit	BSS84, BSS284, 2SJ185, 2SJ461
2SJ576	MOS-P-FET-e*	-	35(2mm)	Hit	→2SJ576
2SJ577	MOS-P-FET-e*	V-MOS, 250V, 3A, 50W, <2Ω(5A)	30c$	Sanyo	SFW9634
2SJ578	MOS-P-FET-e*	V-MOS, LogL, 60V, 1A, <1,8Ω(0,5A)	39b	Sanyo	2SJ190, 2SJ238, 2SJ278, 2SJ450, 2SJ508
2SJ579	MOS-P-FET-e*	V-MOS, LogL, 60V, 1,2A, <1,15Ω(0,5A)	39b	Sanyo	2SJ190, 2SJ238, 2SJ278, 2SJ450, 2SJ508
2SJ581	MOS-P-FET-e*	V-MOS, LogL, 60V, ±12A, 1,8W, <185mΩ	78c	Nec	(2SJ329, 2SJ531, 2SJ534, 2SJ546,...)
2SJ583LS	MOS-P-FET-e*	V-MOS, 250V, 3,5A, 30W, <1,5Ω(5A)	17c	Sanyo	SFS9634, 2SJ306, 2SJ320, 2SJ448
2SJ584LS	MOS-P-FET-e*	V-MOS, 250V, 4,5A, 25W, <1,2Ω(2,5A)	17c	Sanyo	IRFI9634, 2SJ320, 2SJ448, 2SJ512
2SJ585LS	MOS-P-FET-e*	V-MOS, 250V, 6,5A, 30W, <0,7Ω(3,5A)	17c	Sanyo	2SJ307, 2SJ308, 2SJ449
2SJ611(-Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±1A 10W, <5Ω(0,5A)	30c$	Nec	2SJ128, 2SJ194
2SJ612(-Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±2A, 20W, <0,45Ω(5A)	30c$	Nec	2SJ128, 2SJ194
2SJ654(-Z)	MOS-P-FET-e	V-MOS, Sw, Pow, 100V, ±1A 10W, <3Ω(0,5A)	30c$	Nec	2SJ128, 2SJ194
2SJ68	P-FET	AF, Sw, LN, 40V, Idss=1,6..12mA, Up<1,5V	7a	Hit	2SJ104, 2SJ107..108
2SJ69	P-FET	AF, Sw, LN, 40V, Idss=2,5..20mA, Up<1,5V	7a	Hit	2SJ104, 2SJ107..108
2SJ70	P-FET	AF, Sw, LN, 40V, Idss=6..50mA, Up<1,5V	7a(9mm)	Hit	2SJ51
2SJ72	P-FET	GenP, 25V, Idss=5..30mA, Up<2V	7a(9mm)	Tos	2SJ110..111
2SJ73	P-FET	=2SJ72: gep.	2x7a(9mm)	Tos	(2x2SJ110..111)
2SJ74	P-FET	GenP, 25V, Idss>1mA, Up<2V	7a	Tos	2N5021
2SJ75	P-FET	=2SJ74: gep.	2x7a	Tos	(2x2N5021)
2SJ76	MOS-P-FET-e*	V-MOS, 140V, 0,5A, 30W, 20/30nS, 10Ω	17d*	Hit	-
2SJ77	MOS-P-FET-e*	=2SJ76: 160V	17d*	Hit	-
2SJ78	MOS-P-FET-e*	=2SJ76: 180V	17d*	Hit	-
2SJ79	MOS-P-FET-e*	=2SJ76: 200V	17d*	Hit	-
2SJ81	MOS-P-FET-e	V-MOS, 120V, 7A, 100W, <1,7Ω, 230/110nS	20d*	Hit	(2SJ99..100)
2SJ82	MOS-P-FET-e	=2SJ81: 140V	20d*	Hit	(2SJ99..100)
2SJ83	MOS-P-FET-e	=2SJ81: 160V	20d*	Hit	(2SJ100)
2SJ84	P-FET	GenP, 15V, Idss=0,5..12mA, Up<3V	35f	Mat	-
2SJ84-P	Si-PNP	-	35	Mat	→2SJ84

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2SJ84-Q	Si-PNP	-	35	Mat	→2SJ84
2SJ84-R	Si-PNP	-	35	Mat	→2SJ84
2SJ85	MOS-P-FET-e	→2SJ76	-	Hit	-
2SJ86	MOS-P-FET-e	→2SJ76	-	Hit	-
2SJ87	MOS-P-FET-e	→2SJ76	-	Hit	-
2SJ90	P-FET	Dual,30V,Idss=2,6..20mA,Up>2V	7-SIP/bp1	Tos	-
2SJ91	MOS-P-FET-e	V-MOS,Pow,140V,8A,120W	23a$	Tos	2SJ114..115,2SJ118..119,(2SJ55..56)
2SJ92	MOS-P-FET-e	=2SJ91:7A,100W	18c$	Tos	2SJ114..115,2SJ118..119
2SJ96	MOS-P-FET-e	V-MOS,60V,8A,100W,<0,8e,100/250nS	20d*	Hit	2SJ81..83,(2SJ99..100)
2SJ99	MOS-P-FET-e	V-MOS,140V,8A,100W,<0,5Ω,100/90nS	20c$	Hit	(2SJ82..83)
2SK1000	N-FET	AM-Tuner,22V,50mA,Idss>10mA,Up<2,5V	40a	Nec	-
2SK1001	N-FET	=2SK1000:SMD	35f	Nec	-
2SK1001-X41	N-FET	-	35	Nec	→2SK1001
2SK1001-X42	N-FET	-	35	Nec	→2SK1001
2SK1001-X43	N-FET	-	35	Nec	→2SK1001
2SK1002	N-FET	20V,Idss=0,12..0,5mA,Up<1V	40a	Nec	-
2SK1006	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,40W,<1,6e(2,5A)	?15c	Fjd	2SK1231..32,2SK1351,2SK1608,2SK1626+
2SK1006-01MR	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,40W,<1,6Ω(2,5A)	17c	Fujitsu	2SK1231..32,2SK1351,2SK1608,2SK1626..
2SK1007(-01)	MOS-N-FET-e	=2SK1006:60W	17c$	Fjd	BUZ41A..42,2SK893,2SK1156,2SK1246,..
2SK1008(-01)	MOS-N-FET-e	=2SK1006:500V,4,5A,60W,<2,2Ω(2,5A)	17c$	Fjd	BUZ41A..42,2SK893,2SK1156,2SK1246,..
2SK1009(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,450V,7A,80W,<1,3Ω(5A)	17c$	Fjd	IRF840,IRF842,2SK894,2SK1495..96,..
2SK1010(-01)	MOS-N-FET-e	=2SK1009:500V,6A,<1,6Ω(5A)	17c$	Fjd	IRF840,IRF842,2SK894,2SK1496..
2SK1011(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,450V,10A,100W,<0,65Ω	18c$	Fjd	BUZ339,2SK896,2SK1488,2SK1785..
2SK1012(-01)	MOS-N-FET-e	=2SK1011:500V,<0,9e(5A)	18c$	Fjd	BUZ339,2SK896,2SK1488,2SK1785..
2SK1013(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,450V,13A,125W,<0,6Ω(5A)	18c$	Fjd	2SK899,2SK1610,2SK1745,2SK1757..
2SK1014(-01)	MOS-N-FET-e	=2SK1013:500V,12A,<0,74Ω(5A)	18c$	Fjd	2SK899,2SK1610,2SK1745,2SK1757..
2SK1015(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,450V,18A,125W,<0,45Ω(5A)	18c$	Fjd	2SK870,2SK1517..18,2SK1499..1500..
2SK1016(-01)	MOS-N-FET-e	=2SK1015:500V,15A,<0,55Ω(5A)	18c$	Fjd	2SK899,2SK1745,2SK1678,2SK1757..
2SK1017(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,450V,20A,150W,<0,35Ω	18c$	Fjd	2SK870,2SK1517..18,2SK1409,2SK1680,..
2SK1018	MOS-N-FET-e	=2SK1017:500V,18A,<0,45Ω(10A)	18c$	Fjd	2SK870,2SK1518,2SK1498,2SK1680,..
2SK1019	MOS-N-FET-e	V-MOS,Sw-Reg,450V,35A,300W,<0,2Ω	77c$	Fjd	2SK1519..20,2SK1628..29
2SK1020	MOS-N-FET-e	=2SK1019:500V,30A,<0,25Ω(10A)	77c$	Fjd	2SK1520,2SK1629
2SK1021	MOS-N-FET-e	V-MOS,Sw-Reg,800V,3A,60W,<6Ω(1,5A)	17c$	Fjd	BUZ81,2SK1501,2SK1639,2SK1643..
2SK1022	MOS-N-FET-e	=2SK1021:900V,2,5A,<7,3Ω(1,5A)	17c$	Fjd	BUK456-1000,2SK791..792,2SK1793..
2SK1023(-01)	MOS-N-FET-e	V-MOS,Sw-Reg,800V,4A,60W,<4,5Ω(5A)	17c$	Fjd	BUZ81,2SK1501,2SK1639,2SK1643..
2SK1024(-01)	MOS-N-FET-e	=2SK1023:900V,3,5A	17c$	Fjd	2SK1457,2SK1501,2SK1639,2SK1643..
2SK1025	MOS-N-FET-e	V-MOS,Sw,Pow,50V,20A,45W,<0,08Ω(10A)	17c	Mitsubishi	BUK445-50,BUZ11F,2SK1095,2SK1420..
2SK1026	MOS-N-FET-e	V-MOS,Sw,Pow,250V,20A,150W,<0,26Ω	?18c$	Mit	2SK901,2SK944,2SK1641,2SK1673..74..
2SK1027	MOS-N-FET-e	=2SK1026:300V,<0,29e(10A)	?18c$	Mit	2SK1409,2SK1674,2SK1680
2SK1028	MOS-N-FET-e	V-MOS,VHF-Pow,100V,6A,Pq=100W(230MHz)	61	Tos	-
2SK1029	MOS-N-FET-e	V-MOS,DC-DC,500V,±10A,200W,<0,5Ω	77c$	Tos	2SK694
2SK103	N-FET	AF/HF-Pre,20V,Idss=0,02..1mA,Up<0,8V	-	Nec	-
2SK1030	MOS-N-FET-e	V-MOS,Sw,Pow,800V,3A,50W,<5Ω(5A)	17c	Matsushita	2SK1356,2SK1460
2SK1030A	MOS-N-FET-e	=2SK1030:900V	17c	-	2SK1356,2SK1460
2SK1031	N-FET	AF,50V,10mA,Idss>0,6mA,Up<5V	35f	Hit	-
2SK1031-B	N-FET	-	35	Hit	→2SK1031
2SK1031-C	N-FET	-	35	Hit	→2SK1031
2SK1031-D	N-FET	-	35	Hit	→2SK1031
2SK1032	MOS-N-FET-e	V-MOS,800V,8A,120W,<1,7Ω(5A)	18c$	Mat	2SK684,2SK1342,2SK1358,2SK1502..
2SK1032A	MOS-N-FET-e	=2SK1032:900V	18c$	-	2SK1342,2SK1358,2SK1462,2SK1614..
2SK1033	MOS-N-FET-e	V-MOS,LogL,60V,±12A,45W,<0,07Ω(10A)	17c	Matsushita	2SK1093,2SK1256,2SK1305..06,2SK1344..
2SK1034	MOS-N-FET-e	V-MOS,LogL,100V,15A,45W,<0,18Ω(5A)	17c	Mat	2SK1306,2SK1558
2SK1035	MOS-N-FET-e	V-MOS,LogL,150V,±12A,45W,<0,3(5A)	17c	Mat	2SK2131
2SK1036	MOS-N-FET-e	V-MOS,250V,±10A,50W,<0,3Ω(5A)	17c	Mat	2SK526,2SK1762,2SK2011,2SK2426
2SK1037	MOS-N-FET-e	V-MOS,250V,50W	17c	Mat	-
2SK1038	MOS-N-FET-e	V-MOS,Sw,Pow,400V,5A,50W,<1,8Ω(5A)	17c	Matsushita	BUK445-400,2SK530,2SK1377,2SK1990..
2SK1039	MOS-N-FET-e	V-MOS,Sw,Pow,400V,8A,50W,<1,4Ω(5A)	17c	Matsushita	2SK1566..67,2SK1609,2SK2116..17..
2SK104	N-FET	GenP,30V,Idss=0,5..12mA,Up<4,5V	7f	Nec	BFS70,2N3821,2N4220,2N5359,2SK104..
2SK1040	MOS-N-FET-e	V-MOS,Sw,Pow,400V,10A,100W,<1Ω(5A)	16c($)	Mat	BUZ326,BUZ351,2SK556,2SK634
2SK1041	MOS-N-FET-e	V-MOS,Sw,Pow,400V,15A,120W,<0,55Ω	-	Mat	BUK637-400,BUZ323
2SK1042	MOS-N-FET-e	V-MOS,Sw,Pow,400V,20A,130W,<0,45Ω	-	Mat	2SK868
2SK1043	GaAs-N-FET-d	UHF,X..Ku-Band,4V,Idss=12..60mA,12G	51y	Nec	-
2SK1044	MOS-N-FET-e	V-MOS,Sw,Pow,800V,5A,150W,<1,7Ω(2,5A)	?18c$	Mit	2SK727,2SK793,2SK1461,2SK1649..50,..
2SK1045	MOS-N-FET-e	=2SK1044:900V,<2Ω(2,5A)	?18c$	Mit	2SK727,2SK794,2SK1341,2SK1649..50..

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2SK1046	GaAs-N-FET-d	UHF, C..K-Band, 4V, 70mA, 12GHz	51y	Nec	-
2SK1047	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 20A, 150W, <0,26Ω	?18c$	Mit	2SK901, 2SK944, 2SK1673..74, 2SK1641
2SK1048	MOS-N-FET-e	=2SK1047: 300V, <0,29e(10A)	?18c$	Mit	2SK868(A), 2SK1674
2SK1049	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 15A, 150W, <0,65Ω(5A)	?18c$	Mit	2SK899, 2SK1610, 2SK1678, 2SK1745..
2SK105	N-FET	=2SK104: 50V	7a	Nec	-
2SK1050	MOS-N-FET-e	=2SK1049: 500V, <0,78Ω(5A)	?18c$	Mit	2SK899, 2SK1610, 2SK1678, 2SK1745..
2SK1051	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 40A, 120W, <0,03Ω(20A)	?18c$	Mit	BUZ347..348, 2SK857, 2SK905, 2SK1124,..
2SK1052	MOS-N-FET-e	V-MOS, Pow, 450V, 0,5A, 30W, <7Ω(0,5A)	17c$	Sanyo	-
2SK1053	MOS-N-FET-e	V-MOS, Pow, 450V, 1A, 40W, <4,5Ω(0,5A)	17c$	Sanyo	-
2SK1056	MOS-N-FET-e*	V-MOS, 120V, 7A, 100W, 180/60nS	18d*,c$(?)	Hit	(2SK405, 2SK413..414)
2SK1057	MOS-N-FET-e*	=2SK1056: 140V	18d*,c$(?)	Hit	(2SK405, 2SK413..414)
2SK1058	MOS-N-FET-e*	=2SK1056: 160V	18d*,c$(?)	Hit	(2SK400)
2SK1059(-Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, ±5A, 20W, <0,135Ω(5A)	30c$	Nec	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK106	N-FET	GenP, 50V, Idss=0,5..12mA, Up<1,5V	7a	Hit	2SK68, 2SK121, 2SK163, 2SK170, 2SK184
2SK1060(-Z)	MOS-N-FET-e	=2SK1059: 100V, <0,27Ω(5A)	30c$	Nec	2SK1474, 2SK1804, 2SK2016, 2SK2399
2SK1061	MOS-N-FET-e	=2SK982: 0,3W	41c	Tos	BS170, BST170, 2SK422..423
2SK1062	N-FET	-	35	Tos	→2SK1062
2SK1063	MOS-N-FET-e*	=2SK559: 125W	23a$	Hit	2SK788, 2SK899, 2SK1610, 2SK1678..
2SK1064	MOS-N-FET-e*	=2SK560: 125W	23a$	Hit	2SK788, 2SK899, 2SK1610, 2SK1678..
2SK1065	N-FET	-	35	Sanyo	→2SK1065
2SK1065-3	N-FET	-	35(2mm)	Sanyo	→2SK1065
2SK1065-4	N-FET	-	35(2mm)	Sanyo	→2SK1065
2SK1065-5	N-FET	-	35(2mm)	Sanyo	→2SK1065
2SK1066	N-FET	-	35	Sanyo	→2SK1066
2SK1066-20	N-FET	-	35(2mm)	Sanyo	→2SK1066
2SK1066-21	N-FET	-	35(2mm)	Sanyo	→2SK1066
2SK1066-22	N-FET	-	35(2mm)	Sanyo	→2SK1066
2SK1067	MOS-N-FET-d	-	35(2mm)	Sanyo	→2SK1067
2SK1068	N-FET	-	35(2mm)	Sanyo	→2SK1068
2SK1069	N-FET	-	35(2mm)	Sanyo	→2SK1069
2SK107	N-FET	FM/VHF, 27V, Idss>2,7mA, Up<3,85V	7e	Son	BF410B, 2SK192
2SK1070	N-FET	=2SK435: SMD	35f	Hit	-
2SK1070-B	N-FET	-	35	Hit	→2SK1070
2SK1070-C	N-FET	-	35	Hit	→2SK1070
2SK1070-D	N-FET	-	35	Hit	→2SK1070
2SK1070-E	N-FET	-	35	Hit	→2SK1070
2SK1073	MOS-N-FET-e	=2SK1074: Iso, 45W	17c	Mit	2SK1356, 2SK1460
2SK1074	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 120W, <3,6Ω(1,5A)	?18c$	Mit	2SK603, 2SK726, 2SK954, 2SK1339
2SK1078	MOS-N-FET-e	-	39	Tos	→2SK1078
2SK1079	MOS-N-FET-e	-	39	Tos	→2SK1079
2SK108	N-FET	GenP, LN, 50V, Idss=1..12mA, Up<3V	7e	Mit	BF410B, BFW12, 2N4340, 2N5484..
2SK1081(-01)	MOS-N-FET-e	V-MOS, Sw-Reg, 800V, 7A, 125W, <2,2Ω(5A)	18c$	Fjd	BUK638-800, 2SK684, 2SK1032, 2SK1502,..
2SK1082(-01)	MOS-N-FET-e	=2SK1081: 6A, <2,8Ω(5A)	18c$	Fjd	BUK638-800, 2SK684, 2SK1032, 2SK1502,..
2SK1083	MOS-N-FET-e	V-MOS, LogL, 60V, 8A, 20W, <0,35Ω(4A)	?15c	Fjd	BUK542-60, 2SK1261, 2SK1556
2SK1083(-M,MR)	MOS-N-FET-e	V-MOS, LogL, 60V, 8A, 20W, <0,35Ω(4A)	17c	Fujitsu	BUK542-60, 2SK1261, 2SK1556
2SK1084	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 5A, 20W, <0,5Ω(2,5A)	?15c	Fjd	BUK542-100, 2SK1260, 2SK1265
2SK1085	MOS-N-FET-e	V-MOS, LogL, 150V, 3A, 20W, <1,17e	?15c	Fjd	2SK1264..1265, 2SK2588
2SK1085(-M,MR)	MOS-N-FET-e	V-MOS, LogL, 150V, 3A, 20W, <1,17e	17c	Fjd	2SK1264..1265, 2SK2588
2SK1086	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 20A, 35W, <0,07e(10A)	?15c	Fjd	2SK943, 2SK1214, 2SK1345, 2SK1951, +
2SK1086-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 20A, 35W, <0,07Ω(10A)	17c	Fujitsu	2SK943, 2SK1214, 2SK1345, 2SK1951..
2SK1087	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 12A, 35W, <0,17e(6A)	?15c	Fjd	2SK1034, 2SK1306, 2SK1558
2SK1087-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 12A, 35W, <0,17Ω(6A)	17c	Fujitsu	2SK1034, 2SK1306, 2SK1558
2SK1088	MOS-N-FET-e	V-MOS, LogL, 150V, 9A, 35W, <0,4e	?15c	Fjd	BUK545-200, IRLS640A, 2SK1035, 2SK2161
2SK1088(-M,MR)	MOS-N-FET-e	V-MOS, LogL, 150V, 9A, 35W, <0,4e	17c	Fjd	BUK545-200, IRLS640A, 2SK1035, 2SK2161
2SK1089	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 35A, 80W, <0,035Ω	18c$	Fjd	2SK1297, 2SK1514, 2SK1665
2SK109(A)	N-FET	=2SK108: Dual	7-SIP/bp1	Mit	-
2SK1090	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 20A, 80W, <0,08Ω(10A)	18c$	Fjd	2SK1267
2SK1091	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, 15A, 80W, <0,15Ω	18c$	Fjd	2SK1267
2SK1092	GaAs-N-FET	-	44	Hit	→2SK1092
2SK1093	MOS-N-FET-e*	=2SK970: Iso, 20W	17c	Hit	2SK1033, 2SK1256, 2SK1305..06, 2SK1344
2SK1094	MOS-N-FET-e*	=2SK971: Iso, 25W	17c	Hit	2SK1034, 2SK1306, 2SK1345, 2SK1558
2SK1095	MOS-N-FET-e*	=2SK972: Iso, 30W	17c	Hit	2SK943, 2SK1345..46, 2SK1348..49
2SK1096	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 13A, 30W, <0,12e(7A)	?15c	Fjd	2SK1034, 2SK1306, 2SK1558
2SK1096-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 13A, 30W, <0,12Ω(7A)	17c	Fujitsu	2SK1034, 2SK1306, 2SK1558

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2SK1097	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 8A, 30W, <0,28Ω(5A)	?15c	Fjd	BUK543-100, 2SK1261, 2SK1556
2SK1098	MOS-N-FET-e	V-MOS, LogL, 150V, 6A, 30W, <0,65e(3A)	?15c	Fjd	BUK545-200, 2SK1265, 2SK2160, 2SK2161
2SK1098(-M,MR)	MOS-N-FET-e	V-MOS, LogL, 150V, 6A, 30W, <0,65e(3A)	17c	Fjd	BUK545-200, 2SK1265, 2SK2160, 2SK2161
2SK1099	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 80W, <0,67Ω(5A)	18c	Fjd	2SK1206, 2SK1523, 2SK1696, 2SK1832
2SK11	N-FET	GenP, 20V, Idss=0,3..6,5mA, Up<6V	5g	Tos	BFS70, 2N3369, 2N3821, 2SK381..
2SK110	N-FET	GenP, LN, 30V, 50mA, Idss>2,5mA, Up<2V	7a(9mm)	Mit	BC264A..D, BF410B..D, 2SK192..
2SK1100	GaAs-N-FET	UHF, Ku-Band, 4V, 60mA, 12GHz	51y	Mat	-
2SK1101	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 10A, 50W, <0,65e(5A)	?15c	Fjd	-
2SK1101-01MR	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 10A, 50W, <0,65Ω(5A)	17c	Fujitsu	-
2SK1102	MOS-N-FET-e	=2SK1101: 500V, <0,9e(5A)	?15c	Fjd	-
2SK1102-01MR	MOS-N-FET-e	=2SK1101: 500V, <0,9e(5A)	17c	Fjd	-
2SK1103	N-FET	=2SK1104: SMD	35f	Mat	-
2SK1103-0	N-FET	-	35	Mat	→2SK1103
2SK1103-P	N-FET	-	35	Mat	→2SK1103
2SK1103-Q	N-FET	-	35	Mat	→2SK1103
2SK1103-R	N-FET	-	35	Mat	→2SK1103
2SK1104	N-FET	65V, ±20mA, Idss=0,2..6mA, Up<3,5V	40e	Mat	-
2SK1105(-R)	MOS-N-FET-e	V-MOS, Sw-Reg, 800V, 3A, 80W, <0,4Ω(1,5A)	18c	Fjd	BUK426-800
2SK1108	N-FET	Cond-Microphone-Preamp, 20V, 10mA, Idss>0,04mA	40a	Nec	-
2SK1109	N-FET	=2SK1108: SMD	?35b	Nec	-
2SK111	N-FET	=2SK110: Dual	7-SIP/bp1	Mit	-
2SK1112	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,16Ω	30c$	Tos	2SK1471, 2SK1719, 2SK1949
2SK1113	MOS-N-FET-e	V-MOS, LogL, 120V, 3A, 20W, <0,42Ω	30c$	Tos	2SK1474
2SK1114	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 40W, <0,07Ω(5A)	17c$	Tos	BUK552-60, 2SK970..971, 2SK1300
2SK1115	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 60W, <0,055Ω	17c$	Tos	2SK942, 2SK972, 2SK1287, 2SK1910
2SK1116	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 100W, <0,058Ω	17c$	Tos	BUK555-100, 2SK1347, 2SK1293, 2SK2050
2SK1117	MOS-N-FET-e	V-MOS, Sw-Reg, 600V, 6A, 100W	17c$	Tos	BUZ90, 2SK1402, 2SK1501, 2SK1639, 2SK1643
2SK1118	MOS-N-FET-e	=2SK1117: Iso, 45W	17c	Tos	2SK1404, 2SK1637, 2SK2044
2SK1119	MOS-N-FET-e	V-MOS, SMPS, (240V), 1000V, 4A, 100W	17c$	Tos	-
2SK112	N-FET	GenP, LN, 50V, Idss>1,2mA, Up<1,2V	2b&	Tos	-
2SK1120	MOS-N-FET-e	V-MOS, SMPS, (240V), 1000V, 8A, 150W	18c$	Tos	2SK1934
2SK1121	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 25A, 45W, <0,03Ω(10A)	17c	Mitsubishi	BUK545-50, 2SK943, 2SK1345
2SK1122	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 100W, <50mΩ	18c$	Nec	2SK1263, 2SK1304
2SK1123	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 100W, <27mΩ	18c$	Nec	2SK1297, 2SK1514, 2SK1665
2SK1124	MOS-N-FET-e	V-MOS, 60V, 45A, 125W, <0,03Ω(20A)	18c$	Tos	BUK439-60, 2SK849, 2SK857, 2SK1379..
2SK113	N-FET	GenP, 50V, Idss=5..150mA, Up<10V	2b&	Tos	-
2SK1131	N-FET	GenP, 20V, Idss=0,15..0,8mA	41e	Sanyo	-
2SK1132	MOS-N-FET-e*	V-MOS, 50V, ±0,1A, 0,25W, <50Ω(20mA)	40c	Nec	BSS100
2SK1133	MOS-N-FET-e	-	35	Nec	→2SK1133
2SK1134	MOS-N-FET-e	V-MOS, DC-DC, 50V, 45A, 80W, <0,03Ω	18c(p)	Fjd	BUZ347, 2SK905, 2SK1379, 2SK1514..
2SK1135	MOS-N-FET-e*	V-MOS, 250V, 15A, 100W, <0,22Ω(5A)	18c$	Hit	2SK1401
2SK1136	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 10A, 30W, <0,06Ω(5A)	17c	Mitsubishi	BUK543-50, 2SK1256, 2SK1344
2SK1137	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 16A, 40W, <0,035Ω(5A)	17c	Mitsubishi	BUK545-50, 2SK943, 2SK1214, 2SK1345..46
2SK1138	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, 7A, 30W, <0,3Ω(5A)	17c	Mitsubishi	BUK545-200
2SK1139	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, 13A, 40W, <0,08Ω(5A)	17c	Mitsubishi	2SK1266
2SK1142	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 2A, 35W, <5Ω(5A)	17c	Mitsubishi	BUK446-800, 2SK1611, 2SK1834, 2SK1459
2SK1143	MOS-N-FET-e	=2SK1142: 900V, <6Ω(5A)	17c	Mit	2SK1459, 2SK1275
2SK1149	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 75W, <50mΩ(20A)	18c	Nec	-
2SK1150	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 75W, <27mΩ(20A)	18c	Nec	2SK1298, 2SK1666
2SK1151(L,S)	MOS-N-FET-e*	V-MOS, 450V, 1,5A, 20W, <5,5Ω(5A)	30c$	Hit	2SK579..80, 2SK1327, 2SK1672
2SK1152(L,S)	MOS-N-FET-e*	=2SK1151: 500V, <6Ω(5A)	30c$	Hit	2SK580, 2SK1327, 2SK1672
2SK1153	MOS-N-FET-e*	V-MOS, 450V, 3A, 30W, <2,8Ω(5A)	17c$	Hit	BUZ41A..42, 2SK1244, 2SK1493..94
2SK1154	MOS-N-FET-e*	=2SK1153: 500V, <3Ω(5A)	17c$	Hit	BUZ41A..42, 2SK1244, 2SK1494
2SK1155	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4Ω(2,5A)	17c$	Hit	BUZ41A..42, IRF830, 2SK893, 2SK1246,..
2SK1156	MOS-N-FET-e*	=2SK1155: 500V, <1,5Ω(2,5A)	17c$	Hit	BUZ41A..42, IRF830, 2SK893, 2SK1246,..
2SK1157	MOS-N-FET-e*	V-MOS, 450V, 7A, 60W, <0,8Ω(5A)	17c$	Hit	IRF840, 2SK894, 2SK1495..96, 2SK1574,..
2SK1158	MOS-N-FET-e*	=2SK1157: 500V, <0,9e(5A)	17c$	Hit	IRF840, 2SK894, 2SK1496, 2SK1574,..
2SK1159	MOS-N-FET-e*	V-MOS, 450V, 8A, 60W, <0,7Ω(5A)	17c$	Hit	IRF840, 2SK894, 2SK1495..96, 2SK1574,..
2SK1160	MOS-N-FET-e*	=2SK1159: 500V, <0,8Ω(5A)	17c$	Hit	IRF840, 2SK894, 2SK1496, 2SK1574,..
2SK1161	MOS-N-FET-e*	V-MOS, 450V, 10A, 100W, <0,8Ω(5A)	18c$	Hit	2SK724, 2SK896, 2SK1488, 2SK1752,..
2SK1162	MOS-N-FET-e*	=2SK1161: 500V, <0,9e(5A)	18c$	Hit	2SK724, 2SK896, 2SK1488, 2SK1753,..
2SK1163	MOS-N-FET-e*	V-MOS, 450V, 11A, 100W, <0,7Ω(5A)	18c$	Hit	2SK724, 2SK896, 2SK1488, 2SK1752,..
2SK1164	MOS-N-FET-e*	=2SK1163: 500V, <0,8Ω(5A)	18c$	Hit	2SK724, 2SK896, 2SK1488, 2SK1753,..
2SK1165	MOS-N-FET-e*	V-MOS, 450V, 12A, 100W, <0,55Ω(5A)	18c$	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745

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2SK1166	MOS-N-FET-e*	=2SK1165: 500V, <0,6(5A)	18c$	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1167	MOS-N-FET-e*	V-MOS, 450V, 15A, 100W, <0,36Ω(5A)	18c$	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1168	MOS-N-FET-e*	=2SK1167: 500V, <0,4Ω(5A)	18c$	Hit	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1169	MOS-N-FET-e*	V-MOS, 450V, 20A, 120W, <0,25Ω(10A)	18c$	Hit	2SK870, 2SK1409, 2SK1411, 2SK1497..1500+
2SK117	N-FET	AF, LN, 50V, Idss>0,6mA, Up<1,5V	7a	Tos	2SK68, 2SK106, 2SK121, 2SK163, 2SK184,..
2SK1170	MOS-N-FET-e*	=2SK1169: 500V, <0,27Ω(10A)	18c$	Hit	2SK870, 2SK1411, 2SK1498, 2SK1500..
2SK1171	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 4A, 80W, <4,5Ω(5A)	18c$	Fjd	2SK695, 2SK727, 2SK793..94, 2SK1649..50+
2SK1172	MOS-N-FET-e	=2SK1171: 900V, 3,5A, <5,5Ω(5A)	18c$	Fjd	2SK794, 2SK1341, 2SK1649..50, 2SK1760
2SK1173	MOS-N-FET-e	50V, 0,5A, 0,2W	-	Mat	-
2SK1174	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 2,5A, 40W, <4Ω	17c	Sanken	2SK1459
2SK1175	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 4,5A, 85W, <2,5Ω	18c	Sak	2SK809A, 2SK1463, 2SK1684
2SK1176	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 6,5A, 85W, <1,6Ω	18c	Sak	2SK1464, 2SK1685
2SK1177	MOS-N-FET-e	V-MOS, 500V, ±2,5A, 30W, <3Ω(1,5A)	17c	Sak	BUK444-500, 2SK1758, 2SK1833
2SK1178	MOS-N-FET-e	V-MOS, 500V, ±4A, 35W, <1,5Ω(5A)	17c	Sak	2SK1232, 2SK1627, 2SK1993, 2SK2115
2SK1179	MOS-N-FET-e	V-MOS, 500V, n8,5A, 85W, <0,85Ω(4,5A)	18c	Sak	2SK1329, 2SK1523, 2SK1696, 2SK1832
2SK118	N-FET	GenP, 50V, Idss>0,3mA, Up<1,5V	41e	Tos	2SK68, 2SK106, 2SK184
2SK1180	MOS-N-FET-e	V-MOS, 500V, ±10A, 85W, <0,6Ω(5A)	18c	Sak	2SK1329, 2SK1523, 2SK1696, 2SK1832
2SK1181	MOS-N-FET-e	V-MOS, 500V, n13A, 85W, <0,4Ω(6,5A)	18c	Sak	2SK1269, 2SK1331, 2SK1524, 2SK2195
2SK1182	MOS-N-FET-e	V-MOS, 500V, 16A, 90W, <0,27Ω	18c	Sak	2SK1269, 2SK1524
2SK1183	MOS-N-FET-e	V-MOS, 200V, ±3A, 25W, <1,5Ω(1,5A)	17c	Sak	BUZ73(A)F, 2SK2010, 2SK2108, 2SK2381
2SK1184	MOS-N-FET-e	V-MOS, 200V, ±5A, 30W, <0,8Ω(2,5A)	17c	Sak	BUZ73(A)F, 2SK2010, 2SK2108, 2SK2381
2SK1185	MOS-N-FET-e	V-MOS, 100V, ±5A, 25W, <0,54Ω(2,5A)	17c	Sak	BUK442-100, BUK542-100, 2SK1260
2SK1186	MOS-N-FET-e	V-MOS, 100V, ±9A, 30W, <0,27Ω(4,5A)	17c	Sak	BUK443-100, BUK543-100, 2SK1430..
2SK1187	MOS-N-FET-e	V-MOS, 100V, ±12A, 35W, <0,16Ω(5A)	17c	Sak	BUK545-100, 2SK1430..31, 2SK1558..
2SK1188	MOS-N-FET-e	V-MOS, 60V, ±10A, 25W, <0,2Ω(5A)	17c	Sak	BUK442-60, 2SK1033, 2SK1093, 2SK1974,..
2SK1189	MOS-N-FET-e	V-MOS, 60V, ±15A, 30W, <0,1Ω(5A)	17c	Sak	BUK445-60, 2SK1094, 2SK1286, 2SK1419
2SK119	N-FET	GenP, 30V, 20mA, Idss>0,5mA, Up<4,5V	2a&	Nec	BFS70, 2N3821, 2N4220, 2N5359, 2SK104..
2SK1190	MOS-N-FET-e	V-MOS, 60V, ±22A, 35W, <0,05Ω(10A)	17c	Sak	BUK445-60, 2SK1095, 2SK1420, 2SK1951,..
2SK1191	MOS-N-FET-e	V-MOS, 60V, ±30A, 40W, <28mΩ(10A)	17c	Sak	2SK1257, 2SK1421, 2SK1653, 2SK1952..
2SK1192	MOS-N-FET-e	V-MOS, 60V, ±40A, 90W, <28mΩ(20A)	18c	Sak	2SK1298, 2SK1424, 2SK1666, 2SK2203
2SK1193	MOS-N-FET-e	V-MOS, 60V, 45A, 95W, <20me	18c	Sak	2SK1298, 2SK1424, 2SK1666, 2SK2203
2SK1194	MOS-N-FET-e	V-MOS, Sw, Pow, 230V, 0,5A, 6W, <8Ω(0,5A)	30c$	Shi	2SK1838, 2SK2199
2SK1195	MOS-N-FET-e	V-MOS, Sw, Pow, 230V, 1,5A, 10W, <2Ω(1,5A)	30c$	Shi	2SK375, 2SK535, 2SK945, 2SK1838
2SK1196	GaAs-N-FET	UHF, 6V, 70mA, Idss=20..70mA, 12GHz	51y	Mat	-
2SK1197	MOS-N-FET-e*	V-MOS, HF-Osc, 100V, 0,5A, 20W, <50Ω	14b, f(?)	Hit	-
2SK1198	MOS-N-FET-e	V-MOS, Sw, Pow, 700V, ±2A, 35W, <3,2Ω(5A)	17c	NEC	BUK446-800, 2SK1459, 2SK1611, 2SK1834..
2SK1199	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(5A), 70/125nS	17c$	Hit	BUZ50, 2SK1324, 2SK1338
2SK12	N-FET	GenP, LN, 20V, Idss=0,45..5mA, Up<4,5V	5g	Tos	BFS70, 2N3821, 2N4220, 2SK104..
2SK120	N-FET	FM/VHF, 15V, 15mA, Idss>1mA, Up>0,3V	7f	Son	BF410A..B, 2N5484, 2SK192
2SK1200	MOS-N-FET-e*	V-MOS, 900V, 3A, 80W, <7Ω(1,5A)	18c$	Hit	2SK726, 2SK794, 2SK1339, 2SK1341
2SK1201	MOS-N-FET-e*	V-MOS, 900V, 4A, 80W, <5,5Ω(5A)	18c$	Hit	BUZ357..358, 2SK727, 2SK1341, 2SK1760..
2SK1202	MOS-N-FET-e*	V-MOS, 900V, 5A, 100W, <4Ω(5A)	18c$	Hit	BUZ357..358, 2SK727, 2SK1341, 2SK1760..
2SK1203	MOS-N-FET-e*	V-MOS, 900V, 6A, 100W, <3Ω(5A)	18c$	Hit	2SK1342, 2SK1358, 2SK1502, 2SK1614..
2SK1204	MOS-N-FET-e*	V-MOS, 900V, 8A, 100W, <1,6Ω(5A)	18c$	Hit	2SK1342, 2SK1358, 2SK1502, 2SK1614...
2SK1205	MOS-N-FET-e*	V-MOS, 1000V, 5A, 100W, <2Ω(5A)	18c$	Hit	BUZ357..358, 2SK685, 2SK1359
2SK1206	MOS-N-FET-e*	=2SK557: Iso, 60W	?18c	Hit	2SK1331, 2SK1523..24
2SK121	N-FET	GenP, LN, 30V, Idss>0,9mA, Up<1,49V	7a, 7e	Son	BF410A..B, 2N4340, 2SK163, 2SK170..
2SK1211	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 2,5A, 40W, <7Ω(5A)	18c	Fjd	BUK426-800
2SK1212(-01R)	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 5A, 80W, <2,5Ω(2,5A)	18c	Fjd	2SK1175..76, 2SK1463, 2SK1684, 2SK2147..
2SK1213	MOS-N-FET-e	V-MOS, 600V, 6A, 125W, <1,25Ω(5A)	18c$	Tos	BUZ332A, 2SK684, 2SK1032, 2SK1925
2SK1214	MOS-N-FET-e	V-MOS, LogL, 80V, ±20A, 45W, <90mΩ(5A)	17c	Matsushita	2SK1307, 2SK1348..49, 2SK1906, 2SK2391
2SK1215	MOS-N-FET-d	=2SK359: SMD	35c(2mm)	Hit	-
2SK1215-D	MOS-N-FET-d	-	35(2mm)	Hit	→2SK1215
2SK1215-E	MOS-N-FET-d	-	35(2mm)	Hit	→2SK1215
2SK1215-F	MOS-N-FET-d	-	35(2mm)	Hit	→2SK1215
2SK1216	N-FET	Video-Camera, 10V, 50mA, Idss>9,2mA	35f	Mat	-
2SK1217	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 8A, 100W, <2Ω(5A)	18c	Fjd	2SK1464, 2SK1685, 2SK1775
2SK1221	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 10A, 80W, <0,4Ω(5A)	17c$	Fjd	2SK925..26, 2SK1393
2SK1222	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 15A, 125W, <0,55Ω(5A)	18c$	Fjd	2SK725, 2SK788, 2SK899, 2SK1610..
2SK1223	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 130W, <45mΩ(10A)	77c$	Mat	2SK1380
2SK1224	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 4A, 50W, <4,5Ω(5A)	17c($)	Fjd	2SK1501, 2SK1639, 2SK1643
2SK1225	MOS-N-FET-e*	=2SK556: Iso, 60W	?18c	Hit	2SK1268..69, 2SK1328, 2SK1523..24
2SK1227	N-FET	Microphone Amplifier 15V, Zin>200Me, Ur<40mV	41a	Tos	-
2SK1228	MOS-N-FET-e	Sw, 50V, ±50mA, <50Ω(10mA)	35a	Mat	BSS138, BSS145, BST82

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2SK1229	GaAs-N-FET	SHF,4V,60mA,Idss=12..60mA,12GHz	51y	Hit	-
2SK123	N-FET	20V,2mA,Idss=130..375mA	?35b	Mat	-
2SK1230	MOS-N-FET-e*	=2SK551:Iso,25W	17c	Hit	2SK525,2SK1035
2SK1231	MOS-N-FET-e*	=2SK552:Iso,30W	17c	Hit	2SK1351,2SK1608,2SK1626..27
2SK1232	MOS-N-FET-e*	=2SK553:Iso,30W	17c	Hit	2SK1351,2SK1608,2SK1627
2SK1233	GaAs-N-FET	UHF,4GHz,6V,0,1A,Idss=20..90mA	51y	Sanyo	-
2SK1234	GaAs-N-FET	UHF,4GHz,5V,0,1A,Idss=20..80mA	51y	Sanyo	-
2SK1235	GaAs-N-FET	UHF,12GHz,6V,0,1A,Idss=20..90mA	51y	Sanyo	-
2SK1236	GaAs-N-FET	UHF,12GHz,6V,0,1A,Idss=20..90mA	51y	Sanyo	-
2SK1237	GaAs-N-FET	UHF,12GHz,5V,0,1A,Idss=20..80mA	51y	Sanyo	-
2SK1238	GaAs-N-FET	UHF,12GHz,5V,0,07A,Idss=20..60mA	51y	Sanyo	-
2SK1239	GaAs-N-FET	=2SK1238:Fig.→	52y	Sanyo	-
2SK124	GaAs-N-FET	UHF,X-Band,8V,0,1A,12GHz	52y*	Nec	-
2SK1240	GaAs-N-FET	UHF,X-Band,0,06A,Idss=10..60mA	51y	Sanyo	-
2SK1241	GaAs-N-FET	UHF,X-Band,0,06A,Idss=10..60mA	51y	Sanyo	-
2SK1242	GaAs-N-FET	=2SK1240:Fig.→	52y	Sanyo	-
2SK1243	GaAs-N-FET	=2SK1241:Fig.→	52y	Sanyo	-
2SK1244	MOS-N-FET-e	V-MOS,500V,3A,40W,<2,3e,45/75nS	17c$	Shi	2SK1154,2SK1494
2SK1245	MOS-N-FET-e	=2SK1244:Iso	15c	Shi	BUK445-500,2SK1572,2SK1767
2SK1246	MOS-N-FET-e	V-MOS,500V,5A,50W,<1,4e,50/90nS	17c$	Shi	BUZ41A,BUZ90,2SK1156,2SK1751,..
2SK1247	MOS-N-FET-e	=2SK1246:Iso	15c	Shi	2SK1232,2SK1351,2SK1608,2SK1627,..
2SK1248	MOS-N-FET-e	V-MOS,500V,10A,100W,<0,7Ω,70/143nS	16c$	Shi	2SK724,2SK896,2SK1488,2SK1753,..
2SK1249	MOS-N-FET-e	V-MOS,500V,15A,130W,<0,45e,100/200nS	16c$	Shi	BUZ338,2SK725,2SK899,2SK1610,2SK1745
2SK125	N-FET	FM/VHF,25V,Idss>30mA,Up<6V	7e	Son	BFT10C
2SK1250	MOS-N-FET-e	V-MOS,500V,20A,150W,<0,35Ω,130/260nS	16c$	Shi	2SK1169..70,2SK1497..1500,2SK1680..
2SK1251	MOS-N-FET-e*	V-MOS,60V,5A,10W,<0,24Ω(2,5A)	?14c	Tos	-
2SK1252	MOS-N-FET-e*	V-MOS,120V,3A,10W,<0,58Ω(1,5A)	?14c	Tos	-
2SK1253	MOS-N-FET-e*	V-MOS,LogL,30V,30A,35W,<0,03Ω(10A)	17c	Hit	2SK1262
2SK1254(L,S)	MOS-N-FET-e*	V-MOS,LogL,100V,3A,20W,<0,4Ω(5A)	30c$	Hit	2SK1113,2SK1284
2SK1255	MOS-N-FET-e	V-MOS,LogL,60V,±5A,30W,<0,2Ω(5A)	17c	Matsushita	BUK541-60,BUK542-100,2SK1260
2SK1256	MOS-N-FET-e	V-MOS,LogL,60V,10A,40W,<0,165Ω(5A)	17c	Matsushita	2SK1033,2SK1093,2SK1305,2SK1344..
2SK1257	MOS-N-FET-e	V-MOS,LogL,60V,40A,45W,<0,05Ω(10)	17c	Matsushita	2SK1653,2SK1952
2SK1258	MOS-N-FET-e	V-MOS,LogL,60V,50A,100W,<45mΩ(13)	18c$	Mat	2SK1379,2SK1381
2SK1259	MOS-N-FET-e	V-MOS,LogL,60V,±100A,150W,<16mΩ(50A)	77c$	Mat	-
2SK1260	MOS-N-FET-e	V-MOS,LogL,100V,5A,30W,<0,6Ω(5A)	17c	Mat	BUK542-100,2SK1265
2SK1261	MOS-N-FET-e	V-MOS,LogL,100V,8A,40W,<0,3Ω(5A)	17c	Mat	BUK543-100,2SK1556
2SK1262	MOS-N-FET-e	V-MOS,LogL,100V,30A,45W,<85mΩ(10A)	17c	Mat	-
2SK1263	MOS-N-FET-e	V-MOS,LogL,100V,40A,100W,<75mΩ(10A)	18c$	Mat	2SK1304,2SK1381
2SK1264	MOS-N-FET-e	V-MOS,LogL,150V,3A,30W,<1,3Ω(5A)	17c	Mat	-
2SK1265	MOS-N-FET-e	V-MOS,LogL,150V,6A,40W,<0,6Ω(5A)	17c	Mat	BUK545-200,2SK1035
2SK1266	MOS-N-FET-e	V-MOS,LogL,150V,±20A,45W,<0,12Ω(10A),90/950nS	17c	Mat	2SK2098
2SK1267	MOS-N-FET-e	V-MOS,LogL,150V,±25A,100W,<0,11Ω(12A),90/830nS	18c$	Mat	2SK1262
2SK1268	MOS-N-FET-e*	=2SK559:Iso,60W	?18c	Hit	2SK1331,2SK1524
2SK1269	MOS-N-FET-e*	=2SK560:Iso,60W	?18c	Hit	2SK1331,2SK1524
2SK127	N-FET	AF,LN,50V,20mA,Idss=0,5..12mA	7a	Mat	-
2SK1270	MOS-N-FET-e	=2SK975:2A,10W	14b	Hit	2SK1283
2SK1271	MOS-N-FET-e	V-MOS,Sw,Pow,1400V,±5A,240W,<4Ω(5A)	18c$	Nec	-
2SK1272	MOS-N-FET-e*	V-MOS,LogL,60V,±1A<0,65Ω(0,5A)	7b	Nec	2SK1274,2SK1733
2SK1273	MOS-N-FET-e*	-	39	Nec	→2SK1273
2SK1274	MOS-N-FET-e*	=2SK1272:±1,5A,1W	9c	Nec	2SK975,2SK1733,2SK1736
2SK1275	MOS-N-FET-e*	=2SK1199:Iso,30W	17c	Hit	2SK1143,2SK1459
2SK1276(A)	MOS-N-FET-e	V-MOS,Sw,Pow,250V,20A,100W,<0,2Ω(10A)	18c$	Fjd	2SK901,2SK944,2SK1641,2SK1673..74
2SK1277	MOS-N-FET-e	V-MOS,Sw,Pow,250V,30A,150W,<0,12Ω(10A)	18c$	Fjd	2SK902,2SK1492,2SK1671,2SK1675..76
2SK1278	MOS-N-FET-e	V-MOS,Sw,Pow,500V,10A,100W,<1,1Ω(5A)	18c$	Fjd	BUZ339,2SK724,2SK896,2SK1488,2SK1753
2SK1279	MOS-N-FET-e	V-MOS,Sw,Pow,500V,15A,125W,<0,58Ω(5A)	18c$	Fjd	BUZ338,2SK725,2SK899,2SK1610,2SK1678
2SK127A	N-FET	=2SK127:80V	7a	-	-
2SK128	N-FET	AF,LN,30V,20mA,Idss>0,5mA,Up<1,5V	7a	Mat	2SK68,2SK106,2SK184
2SK1280	MOS-N-FET-e	V-MOS,Sw,Pow,500V,18A,150W,<0,5Ω(5A)	18c$	Fjd	2SK1409,2SK1411,2SK1680
2SK1281	MOS-N-FET-e	V-MOS,Sw,Pow,700V,4A,120W,<3,2Ω(5A)	18c$	Nec	2SK695,2SK727,2SK793,2SK1649..50..
2SK1282(-Z)	MOS-N-FET-e*	V-MOS,LogL,60V,±3A,20W,<0,18Ω(5A)	30c$	Nec	2SK974,2SK1950
2SK1283	MOS-N-FET-e*	=2SK1282:	14b$	Nec	2SK1285
2SK1284(-Z)	MOS-N-FET-e*	V-MOS,LogL,100V,±3A,20W,<0,32Ω(5A)	30c$	Nec	2SK1113,2SK1254,2SK1299
2SK1285	MOS-N-FET-e*	=2SK1284:	14b$	Nec	-
2SK1286	MOS-N-FET-e*	=2SK1287:Iso,±15A,30W	17c	Nec	2SK943,2SK1214,2SK1345..46

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2SK1287	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 60W, <0,07Ω(10A)	17c$	Nec	2SK972, 2SK942, 2SK1115
2SK1288	MOS-N-FET-e*	=2SK1289: Iso, ±15A, 30W	17c	Nec	2SK1034, 2SK1306, 2SK1292, 2SK1558,..
2SK1289	MOS-N-FET-e*	V-MOS, LogL, 100V, ±20A, 60W, <0,15Ω(10A)	17c$	Nec	2SK1116, 2SK1302, 2SK1347
2SK1290	MOS-N-FET-e*	=2SK1291: Iso, ±25A, 35W	17c	Nec	2SK943, 2SK1214, 2SK1345..46
2SK1291	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 75W, <45mΩ(10A)	17c$	Nec	2SK1296, 2SK2411
2SK1292	MOS-N-FET-e*	=2SK1293: Iso, ±20A, 35W	17c	Nec	2SK1262, 2SK1307, 2SK1348..49
2SK1293	MOS-N-FET-e*	V-MOS, LogL, 100V, ±30A, 75W, <80mΩ(10A)	17c$	Nec	2SK2050, 2SK2314
2SK1294	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 35W, <27mΩ(20A)	17c	Nec	2SK1257, 2SK1653, 2SK1952, 2SK2120
2SK1295	MOS-N-FET-e*	V-MOS, LogL, 100V, ±30A, 75W, <50mΩ(10A)	17c	Nec	2SK1262, 2SK2466, 2SK2577
2SK1296	MOS-N-FET-e*	V-MOS, LogL, 60V, 30A, 75W, <28mΩ(10A)	17c$	Hit	2SK1291
2SK1297	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 100W, <18mΩ(20A)	18c$	Hit	2SK1514, 2SK1665
2SK1298	MOS-N-FET-e	=2SK1297: Iso, 50W	?18c	Hit	2SK1666
2SK1299(L,S)	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, 20W, <0,35Ω(5A)	30c$	Hit	2SK1113, 2SK1254, 2SK1284
2SK13	N-FET	GenP, LN, 12V, Idss=0,45..5mA, Up<4,5V	5g	Tos	BFS70, 2N3821, 2N4220, 2SK104..
2SK130(A)	N-FET	GenP, 30V, 50mA, Idss>5mA, Up<1,5V	7a	Nec	2N5247, 2SK147, 2SK151, 2SK162, 2SK363
2SK1300	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 40W, <0,25Ω(5A)	17c$	Hit	2SK1559, 2SK1561
2SK1301	MOS-N-FET-e*	V-MOS, LogL, 100V, 15A, 50W, <0,13Ω(5A)	17c$	Hit	2SK1559, 2SK1561
2SK1302	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 50W, <85mΩ(10A)	17c$	Hit	BUK555-100, 2SK1116, 2SK1347
2SK1303	MOS-N-FET-e*	V-MOS, LogL, 100V, 30A, 100W, <0,06Ω(10A)	18c$	Hit	2SK1263
2SK1304	MOS-N-FET-e*	V-MOS, LogL, 100V, 40A, 100W, <0,03Ω(20A)	18c$	Hit	2SK1263, 2SK1381
2SK1305	MOS-N-FET-e	=2SK1300: Iso, 25W	17c	Hit	BUK545-100, 2SK1035
2SK1306	MOS-N-FET-e	=2SK1301: Iso, 30W	17c	Hit	2SK1034, 2SK1558
2SK1307	MOS-N-FET-e	=2SK1302: Iso, 35W	17c	Hit	2SK1266, 2SK1292, 2SK1348..49
2SK1308	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 5A, 40W, <1,4Ω(5A)	30c$	Mat	2SK1691
2SK1308A	MOS-N-FET-e	=2SK1308: 450V	30c$	-	2SK1691
2SK131	N-FET	=2SK130: Dual	7e+7a	Nec	-
2SK1310(A)	MOS-N-FET-e	V-MOS, VHF-Pow, 100V, 12A, Pq=190W(230MHz)	-	Tos	-
2SK1311	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, <0,45Ω(5A)	39b	Mat	2SK1273, 2SK1470, 2SK1717, 2SK2315
2SK1313(L,S)	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4Ω(2,5A)	30c$	Hit	2SK1540..41, 2SK1722, 2SK2356Z
2SK1314(L,S)	MOS-N-FET-e	=2SK1313: 500V, <1,5Ω(2,5A)	30c$	Hit	2SK1541, 2SK1722
2SK1315(L,S)	MOS-N-FET-e*	V-MOS, 450V, 8A, 60W, <0,7Ω(5A)	30c$	Hit	2SK2187
2SK1316(L,S)	MOS-N-FET-e*	=2SK1540: 500V, <0,8Ω(5A)	30c$	Hit	2SK2187
2SK1317	MOS-N-FET-e	V-MOS, 1500V, 2,5A, 100W, <12Ω(5A)	18c$	Hit	2SK1835
2SK1318	MOS-N-FET-e*	V-MOS, LogL, 120V, 20A, 35W, <0,12Ω	17c	Hit	2SK1266, 2SK2098
2SK1319	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 8A, 75W, <0,52Ω(5A)	17c$	Mit	2SK741, 2SK1320, 2SK1400
2SK1319..1320S	MOS-N-FET-e	=2SK1319..1322:	30c$	-	2SK1621(250V)
2SK132	MOS-N-FET-e	V-MOS, 100V, 7A, 100W, <1,7Ω, 18/14nS	23e*	Hit	2SK175..176, (BUZ33)
2SK1320	MOS-N-FET-e	=2SK1319: 300V	17c$	Mit	2SK1400
2SK1321	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 5A, 75W, <1,3Ω(5A)	17c$	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751
2SK1321..1322S	MOS-N-FET-e	=2SK1321..1322:	30c$	-	2SK2355Z..56Z
2SK1322	MOS-N-FET-e	=2SK1321: <1,6Ω(5A)	17c$	Mit	BUZ41A..42, 2SK893, 2SK1246, 2SK1751
2SK1323	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 2A, 75W, <6,5Ω(5A)	17c$	Mit	BUZ80, 2SK1199, 2SK1338
2SK1323..1324S	MOS-N-FET-e	=2SK1323..1324:	30c$	-	2SK1647
2SK1324	MOS-N-FET-e	=2SK1323: 900V	17c$	Mit	2SK1199, 2SK1338
2SK1325	GaAs-N-FET	UHF, 6V, 0,12A, Idss=40..120mA, 12GHz	51y	Tos	-
2SK1326	N-FET	Video-Freq., 10V, 20mA, Idss>6mA	35f	Hit	-
2SK1326-D	N-FET	-	35	Hit	→2SK1326
2SK1326-E	N-FET	-	35	Hit	→2SK1326
2SK1327(L,S)	MOS-N-FET-e*	V-MOS, 600V, 1A, 20W, <9e(0,5A)	30c$	Hit	2SK1533, 2SK1880
2SK1328	MOS-N-FET-e*	V-MOS, 450V, 12A, 60W, <0,55Ω(5A)	?18c	Hit	2SK1206, 2SK1225, 2SK1268..69, 2SK1523..
2SK1329	MOS-N-FET-e*	=2SK1328: 500V, <0,6Ω(5A)	?18c	Hit	2SK1206, 2SK1225, 2SK1269, 2SK1523,..
2SK133	MOS-N-FET-e	=2SK132: 120V	23e*	Hit	2SK175..176, (BUZ33)
2SK1330	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 8A, 100W, <1,7Ω(5A)	16c($)	Mat	2SK1032, 2SK1358, 2SK1502, 2SK1692..
2SK1330A	MOS-N-FET-e	=2SK1330: 900V	16c($)	Mat	2SK1358, 2SK1502, 2SK1692, 2SK1795..
2SK1331	MOS-N-FET-e	V-MOS, 500V, 15A, 100W, <0,5Ω(5A)	16c	Mat	2SK1269, 2SK1405, 2SK1524
2SK1332	N-FET	-	35(2mm)	Sanyo	→2SK1332
2SK1333	MOS-N-FET-e	V-MOS, 500V, ±15A, 200W, <0,4Ω(10A)	77c$	Tos	2SK678, 2SK1544
2SK1334	MOS-N-FET-e*	V-MOS, 200V, 1A, <3,8Ω(0,5A), 13/17nS	39b	Hit	-
2SK1335(L,S)	MOS-N-FET-e*	V-MOS, 200V, 3A, 20W, <0,8Ω(5A)	30c$	Hit	-
2SK1336	MOS-N-FET-e*	V-MOS, LogL, 60V, 0,3A, 0,4W, <1,7Ω(0,5A)	7c	Hit	BST70, BST72, 2SK422..423
2SK1337	MOS-N-FET-e*	V-MOS, LogL, 100V, 0,3A, 0,4W, <4,5Ω(0,5A)	7c	Hit	BSS89, BST74, BST76, 2SK423
2SK1338	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(5A)	17c$	Hit	2SK1199, 2SK1324
2SK1339	MOS-N-FET-e*	V-MOS, 900V, 3A, 80W, <7Ω(1,5A)	18c$	Hit	2SK538, 2SK696, 2SK726..727, 2SK794..
2SK134	MOS-N-FET-e	=2SK132: 140V	23e*	Hit	2SK175..176, (BUZ33)

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2SK1340	MOS-N-FET-e*	V-MOS, 900V, 5A, 100W, <4Ω(5A)	18c$	Hit	BUZ357..358, 2SK727, 2SK794, 2SK1760,..
2SK1341	MOS-N-FET-e*	V-MOS, 900V, 6A, 100W, <3Ω(5A)	18c$	Hit	2SK1358, 2SK1462, 2SK1502, 2SK1614..
2SK1342	MOS-N-FET-e*	V-MOS, 900V, 8A, 100W, <1,6Ω(5A)	18c$	Hit	2SK1358, 2SK1462, 2SK1502, 2SK1614..
2SK1344	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 30W, <0,07Ω(5A)	17c	Toshiba	2SK1033, 2SK1094, 2SK1256, 2SK1895..
2SK1345	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 40W, <0,055Ω(10A)	17c	Toshiba	2SK943, 2SK1095, 2SK1214
2SK1346	MOS-N-FET-e	V-MOS, 60V, 25A, 40W, <0,06Ω(10A)	17c	Toshiba	2SK943, 2SK1095, 2SK1214, 2SK1420
2SK1347	MOS-N-FET-e	V-MOS, LogL, 100V, 20A, 75W, <85mΩ	17c$	Tos	BUK555-100, 2SK1302, 2SK1116, 2SK2050
2SK1348	MOS-N-FET-e	=2SK1347: Iso, 40W	17c	Tos	2SK1266, 2SK1307, 2SK1292, 2SK1906
2SK1349	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 45W, <58mΩ	17c	Tos	2SK1262, 2SK1292, 2SK1906
2SK135	MOS-N-FET-e	=2SK132: 160V	23e*	Hit	2SK175..176, (BUZ33)
2SK1350	MOS-N-FET-e	V-MOS, 200V, 15A, 45W, <0,18Ω(10A)	17c	Tos	2SK2012
2SK1351	MOS-N-FET-e	V-MOS, DC-DC, 500V, 5A, 40W, <1,5Ω	17c	Tos	2SK1232, 2SK1608, 2SK1627, 2SK1993..
2SK1352	MOS-N-FET-e	V-MOS, DC-DC, 500V, 7A, 45W, <0,85Ω	17c	Tos	2SK1567, 2SK1805
2SK1356	MOS-N-FET-e	V-MOS, Sw-Reg, 900V, 3A, 40W, <4,3Ω(1,5A)	17c	Toshiba	2SK1460
2SK1357	MOS-N-FET-e	V-MOS, 900V, 5A, 125W, <2,8Ω(5A)	18c$	Tos	2SK727, 2SK794, 2SK1341, 2SK1649..50..
2SK1358	MOS-N-FET-e	V-MOS, 900V, 9A, 150W, <1,4Ω(5A)	18c$	Tos	2SK1342, 2SK1502, 2SK1614, 2SK1796..
2SK1359	MOS-N-FET-e	V-MOS, 1000V, 5A, 125W, <3,8(5A)	18c$	Tos	2SK1205
2SK136	N-FET	GenP, LN, 20mA, 30V, Idss>0,5mA, Up<2V	7a	Mat	2N4339, 2N5358, 2SK83
2SK1360	MOS-N-FET-e	V-MOS, SMPS, 900V, 3A, 80W, <4,3Ω	16c	Tos	2SK1463, 2SK1683, 2SK1770
2SK1362	MOS-N-FET-e	V-MOS, SMPS, 900V, 5A, 85W, <2,5Ω(5A)	16c	Tos	2SK1463..65, 2SK1684..85, 2SK1859,..
2SK1363	MOS-N-FET-e	V-MOS, SMPS, 900V, 8A, 90W, <1,4Ω(5A)	16c	Tos	2SK1464, 2SK1685, 2SK1775
2SK1365	MOS-N-FET-e	V-MOS, SMPS, 1000V, 7A, 90W, <1,8Ω(5A)	16c	Tos	(2SK1120, 2SK1934)
2SK1366	MOS-N-FET-e	V-MOS, 400V, ±2A, 30W, <3,6Ω(5A)	17c	Sak	BUK444-400, 2SK1833, 2SK1988..89
2SK1367	MOS-N-FET-e	V-MOS, 400V, ±3A, 30W, <1,8Ω(1,5A)	17c	Sak	BUK445-450, 2SK1862..63, 2SK1444..
2SK1368	MOS-N-FET-e	V-MOS, 400V, ±5A, 35W, <1Ω(2,5A)	17c	Sak	BUK445-400, 2SK1377, 2SK1992..93..
2SK1369	MOS-N-FET-e	V-MOS, 400V, ±10A, 85W, <0,55Ω(5A)	18c	Sak	2SK1452, 2SK1328..29, 2SK1523..
2SK137(A)	N-FET	AF, Sw, LN, 15V, 50mA, Idss>0,5mA	2f&	Mat	-
2SK1370	MOS-N-FET-e	V-MOS, 400V, ±15A, 85W, <0,3Ω(5A)	18c	Sak	2SK1453, 2SK1268..69, 2SK1524..
2SK1371	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 20A, 125W, <0,25Ω	23a$	Hit	2SK1497, 2SK1499, 2SK1517, 2SK1680..
2SK1372	MOS-N-FET-e	=2SK1371: 500V	23	Hit	-
2SK1373	MOS-N-FET-e	V-MOS, Sw, Pow, 550V, 12A, 100W, <0,67Ω	18c$	Hit	BUZ334, 2SK1723
2SK1374	MOS-N-FET-e*	-	35(2mm)	Mat	→2SK1374
2SK1375	N-FET	-	35(2mm)	Sanyo	→2SK1375
2SK1377	MOS-N-FET-e	V-MOS, DC-DC, 400V, 5,5A, 40W, <1,2Ω	17c	Tos	2SK1231, 2SK1351, 2SK1608, 2SK1627,..
2SK1378	MOS-N-FET-e	V-MOS, DC-DC, 400V, 10A, 125W, <0,55Ω	17c$	Tos	BUZ61
2SK1379	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 150W, <0,017Ω	18c$	Tos	BUK539-60, 2SK1258
2SK138	GaAs-FET	UHF, X-Band, 5V, 100mA, 8GHz	52y	Nec	-
2SK1380	MOS-N-FET-e	V-MOS, LogL, 60V, 60A, 200W, <0,011Ω	77c$	Tos	2SK1259
2SK1381	MOS-N-FET-e	V-MOS, LogL, 100V, 50A, 150W, <0,032Ω	18c$	Tos	BUZ344, IRFP2410, 2SK1434
2SK1382	MOS-N-FET-e	V-MOS, LogL, 100V, 60A, 200W, <0,02Ω	77c$	Tos	-
2SK1383	Si-N-FET-e	Static Inductive Trans., 200V, 3A	2a$	-	-
2SK1384(-R)	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 5A, 80W, <2Ω(2,5A)	18c	Fjd	2SK1175..76, 2SK1463, 2SK1684, 2SK2147
2SK1385(-01)	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 9A, 100W, <1,5Ω(5A)	18c	Fjd	2SK1686, 2SK2148
2SK1386	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 7A, 100W, <1,3Ω(5A)	18c$	Fjd	BUZ330..331
2SK1387	MOS-N-FET-e	V-MOS, 60V, 35A, 40W, <0,035e(17,5A)	?15c	Fjd	2SK1653, 2SK2120, 2SK2312, 2SK2529, +
2SK1387-MR	MOS-N-FET-e	V-MOS, 60V, 35A, 40W, <0,035Ω(17,5A)	17c	Fujitsu	2SK1653, 2SK2120, 2SK2312, 2SK2529..
2SK1388	MOS-N-FET-e	V-MOS, 30V, 35A, 60W, <0,022Ω(17,5A)	17c$	Fjd	BUK555-50
2SK1389	MOS-N-FET-e	V-MOS, 60V, 50A, 125W, <0,025Ω(20A)	18c$	Fjd	2SK1258, 2SK1379
2SK1390(-R)	MOS-N-FET-e	=2SK1389: 80W	18c	Fjd	2SK1298, 2SK1424, 2SK1666, 2SK2203
2SK1391	MOS-N-FET-e	V-MOS, 250V, 6A, 40W, <0,84Ω, 65/65nS	17c$	Shi	2SK477, 2SK741, 2SK924, 2SK1319, 2SK1667
2SK1392	MOS-N-FET-e	=2SK1391: Iso, 25W	15c	Shi	2SK1478, 2SK1568, 2SK1668, 2SK1987..
2SK1393	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,5Ω, 75/100nS	17c$	Shi	2SK925..926, 2SK1221, 2SK1393, 2SK1761..
2SK1394	MOS-N-FET-e	=2SK1393: Iso, 30W	15c	Shi	2SK1036, 2SK1762, 2SK2011, 2SK2426..
2SK1395	MOS-N-FET-e	V-MOS, 250V, 20A, 100W, <0,25Ω(10A)	16c$	Shi	2SK901, 2SK944, 2SK1641, 2SK1673..
2SK1396	MOS-N-FET-e	V-MOS, 250V, 30A, 120W, <0,17Ω(10A)	16c$	Shi	2SK902, 2SK1669, 2SK1671, 2SK1675
2SK1397	MOS-N-FET-e	V-MOS, 250V, 40A, 130W, <0,13Ω(20A)	16c$	Shi	-
2SK1398	MOS-N-FET-e*	V-MOS, Sw, 50V, ±0,1A, 0,25W, <20Ω(10mA)	40c	Nec	BS170, BSS98
2SK1399	MOS-N-FET-e	-	35	Nec	→2SK1399
2SK140	GaAs-FET	UHF, X-Band, 5V, 100mA, 12GHz	52y	Nec	-
2SK1400	MOS-N-FET-e*	V-MOS, 300V, 7A, 50W, <0,7Ω(5A)	17c$	Hit	2SK554..555, 2SK1320
2SK1400A	MOS-N-FET-e*	=2SK1400: 350V, <0,8Ω(5A)	17c$	-	2SK554..555, 2SK1495..96
2SK1401	MOS-N-FET-e*	V-MOS, 300V, 15A, 100W, <0,35Ω(5A)	18c$	Hit	BUZ323
2SK1401A	MOS-N-FET-e*	=2SK1401: 350V, <0,4Ω(5A)	18c$	-	BUZ323
2SK1402	MOS-N-FET-e*	V-MOS, 600V, 4A, 50W, <2,4Ω(5A)	17c$	Hit	BUZ90, 2SK1117

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2SK1402A	MOS-N-FET-e*	=2SK1402:650V,<2,6Ω(5A)	17c$	-	-
2SK1403	MOS-N-FET-e*	V-MOS,600V,8A,100W,<1,3Ω(5A)	18c$	Hit	2SK684,2SK1032
2SK1403A	MOS-N-FET-e*	=2SK1403:650V,<1,4Ω(5A)	18c	-	2SK684,2SK1032
2SK1404	MOS-N-FET-e*	V-MOS,600V,5A,35W,<1,5Ω(2,5A)	17c	Hit	2SK1118,2SK1637
2SK1405	MOS-N-FET-e*	FREDFET,600V,15A,60W,<0,5Ω(5A)	?18c	Hit	2SK2953
2SK1406	MOS-N-FET-e	V-MOS,500V,±20A,100W,<0,4Ω(10A)	16c	Mat	2SK1525
2SK1407	GaAs-N-FET	UHF-Converter,4V,60mA,12GHz	51y	Rhm	-
2SK1408	MOS-N-FET-e	V-MOS,Sw,Pow,450V,16A,200W,<0,31Ω(5A)	?18c$	Mit	-
2SK1409	MOS-N-FET-e	V-MOS,Sw,Pow,450V,20A,250W,<0,25Ω(10A)	?18c$	Mit	-
2SK141(A)	N-FET	GenP,50V,20mA,Idss>0,5mA,Up<4,5V	2b&	Nec	BFS70,2N3821,2N4220,2SK104..
2SK1410	MOS-N-FET-e	=2SK1408:500V	?18c$	Mit	-
2SK1411	MOS-N-FET-e	=2SK1409:500V	?18c$	Mit	-
2SK1412(LS)	MOS-N-FET-e	V-MOS,1500V,0,1A,20W,<200Ω(50(A)	17c	Sanyo	-
2SK1413	MOS-N-FET-e	V-MOS,1500V,2A,60W,<11Ω(5A)	18c	Sanyo	-
2SK1414	MOS-N-FET-e	V-MOS,1500V,6A,200W,<3,5Ω(5A)	77c$	Sanyo	-
2SK1415	GaAs-N-FET-d	SHF,3,5V,60mA,Idss=12..60mA,12GHz	-	Hit	-
2SK1416	MOS-N-FET-e	V-MOS,Sw,Pow,60V,15A,40W,<0,08Ω(10A)	17c$	Sanyo	BUK552-60,2SK971..72,2SK1115
2SK1417	MOS-N-FET-e	V-MOS,Sw,Pow,60V,25A,60W,<45mΩ(10A)	17c$	Sanyo	BUK555-60,2SK972,2SK1115,2SK1296
2SK1418	MOS-N-FET-e	V-MOS,Sw,Pow,60V,40A,70W,<26mΩ(20A)	17c$	Sanyo	BUK556-60,2SK1542
2SK1419	MOS-N-FET-e	V-MOS,Sw,Pow,60V,15A,25W,<0,08Ω(10A)	17c	Sanyo	2SK943,2SK1345..46
2SK1420	MOS-N-FET-e	V-MOS,Sw,Pow,60V,25A,30W,<45mΩ(10A)	17c	Sanyo	2SK943,2SK1345..46
2SK1421	MOS-N-FET-e	V-MOS,Sw,Pow,60V,40A,40W,<26mΩ(20A)	17c	Sanyo	2SK1257,2SK1653
2SK1422	MOS-N-FET-e	V-MOS,60V,50A,100W,<26mΩ(20A)	18c$	Sanyo	BUK539-60,2SK1258,2SK1379
2SK1423	MOS-N-FET-e	V-MOS,60V,80A,150W,<16mΩ(50A)	18c$	Sanyo	IRFP064N
2SK1424	MOS-N-FET-e	V-MOS,Sw,Pow,60V,40A,60W,<26mΩ(20A)	18c	Sanyo	2SK1298,2SK1666
2SK1425	MOS-N-FET-e	V-MOS,Sw,Pow,60V,60A,80W,<16mΩ(50A)	18c	Sanyo	-
2SK1426	MOS-N-FET-e	V-MOS,Sw,Pow,60V,100A,200W,<12mΩ(60A)	77c$	Sanyo	2SK1259
2SK1427	MOS-N-FET-e	V-MOS,Sw,Pow,100V,10A,40W,<0,16Ω(5A)	17c$	Sanyo	2SK1300
2SK1428	MOS-N-FET-e	V-MOS,Sw,Pow,100V,20A,60W,<0,1Ω(10A)	17c$	Sanyo	BUK555-100,2SK1302,2SK1116,2SK1347
2SK1429	MOS-N-FET-e	V-MOS,Sw,Pow,100V,30A,70W,<55mΩ(20A)	17c$	Sanyo	BUK456-100,2SK1303
2SK1430	MOS-N-FET-e	V-MOS,Sw,Pow,100V,10A,25W,<0,16Ω(5A)	17c	Sanyo	BUK545-100,2SK1035,2SK1305
2SK1431	MOS-N-FET-e	V-MOS,Sw,Pow,100V,15A,30W,<0,1Ω(10A)	17c	Sanyo	BUK445-100,2SK1306,2SK1558
2SK1432	MOS-N-FET-e	V-MOS,Sw,Pow,100V,25A,40W,<55mΩ(20A)	17c	Sanyo	2SK1307,2SK1348..49
2SK1433	MOS-N-FET-e	V-MOS,Sw,Pow,100V,30A,100W,<55mΩ(20A)	18c$	Sanyo	2SK1303
2SK1434	MOS-N-FET-e	V-MOS,Sw,Pow,100V,60A,150W,<35mΩ(45A)	18c$	Sanyo	BUZ344,IRFP2410,2SK1381
2SK1435	MOS-N-FET-e	V-MOS,Sw,Pow,100V,30A,60W,<55mΩ(20A)	18c	Sanyo	2SK1149
2SK1436	MOS-N-FET-e	V-MOS,Sw,Pow,100V,50A,80W,<35mΩ(45A)	18c	Sanyo	2SK1149
2SK1437	MOS-N-FET-e	V-MOS,Sw,Pow,100V,70A,200W,<26mΩ(45A)	77c$	Sanyo	2SK1382
2SK1438	MOS-N-FET-e	V-MOS,Sw,Pow,450V,0,3A,20W,<12Ω(0,5A)	17c$	Sanyo	(2SK1052)
2SK1439	MOS-N-FET-e	V-MOS,Sw,Pow,450V,3A,50W,<2,6Ω(1,5A)	17c$	Sanyo	2SK1154,2SK1244
2SK1440	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,60W,<1,4Ω(5A)	17c$	Sanyo	2SK1246,(BUZ41A..42,2SK552..53,2SK893)
2SK1441	MOS-N-FET-e	V-MOS,Sw,Pow,450V,8A,70W,<0,8Ω(5A)	17c$	Sanyo	(2SK554..55,2SK636,2SK894)
2SK1442	MOS-N-FET-e	V-MOS,Sw,Pow,450V,12A,70W,<0,6Ω(5A)	17c$	Sanyo	2SK1503
2SK1443(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,450V,1A,20W,<4,5Ω(0,5A)	17c	Sanyo	2SK1833,(BUK444-450,2SK529,2SK1833)
2SK1444(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,450V,3A,25W,<2,6Ω(1,5A)	17c	Sanyo	BUK445-450,2SK1572,2SK1767
2SK1445(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,30W,<1,4Ω(5A)	17c	Sanyo	2SK1351,2SK1608,2SK1626,2SK1990..93
2SK1446(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,450V,7A,35W,<0,8Ω(5A)	17c	Sanyo	2SK1352,2SK1566..67,2SK1609
2SK1447(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,450V,9A,40W,<0,6Ω(5A)	17c	Sanyo	-
2SK1448	MOS-N-FET-e	V-MOS,Sw,Pow,450V,8A,100W,<0,8Ω(5A)	18c$	Sanyo	2SK1574,(BUZ330..331)
2SK1449	MOS-N-FET-e	V-MOS,Sw,Pow,450V,12A,120W,<0,6Ω(5A)	18c$	Sanyo	2SK1488,2SK1610,2SK1745,2SK1785..
2SK1450	MOS-N-FET-e	V-MOS,Sw,Pow,450V,20A,150W,<0,3Ω(10A)	18c$	Sanyo	2SK1169..70,2SK1497..1500,2SK1680..
2SK1451	MOS-N-FET-e	V-MOS,Sw,Pow,450V,8A,50W,<0,8Ω(5A)	18c	Sanyo	2SK1206,2SK1225,2SK1328,2SK1523
2SK1452	MOS-N-FET-e	V-MOS,Sw,Pow,450V,10A,60W,<0,6Ω(5A)	18c	Sanyo	2SK1206,2SK1225,2SK1328,2SK1523
2SK1453	MOS-N-FET-e	V-MOS,Sw,Pow,450V,16A,70W,<0,3Ω(10A)	18c	Sanyo	2SK1268..69,2SK1331,2SK1524..25
2SK1454	MOS-N-FET-e	V-MOS,Sw,Pow,450V,30A,250W,<0,16Ω(10A)	77c$	Sanyo	2SK1628..29
2SK1455	MOS-N-FET-e	V-MOS,Sw,Pow,900V,0,2A,30W,<70Ω(0,5A)	17c$	Sanyo	-
2SK1456	MOS-N-FET-e	V-MOS,Sw,Pow,900V,3A,60W,<6Ω(1,5A)	17c$	Sanyo	BUK456-1000,2SK1601,2SK1638,2SK1793
2SK1457	MOS-N-FET-e	V-MOS,Sw,Pow,900V,5A,70W,<3,6Ω(5A)	17c$	Sanyo	2SK1501,2SK1639,2SK1643
2SK1458(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,900V,0,2A,20W,<70Ω(0,5A)	17c	Sanyo	-
2SK1459(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,900V,2,5A,30W,<6Ω(1,5A)	17c	Sanyo	2SK1143,2SK1275
2SK146	N-FET	=2SK147:Dual	7e+7a	Tos	-
2SK1460(LS)	MOS-N-FET-e	V-MOS,Sw,Pow,900V,3,5A,40W,<3,6Ω(5A)	17c	Sanyo	2SK1356
2SK1461	MOS-N-FET-e	V-MOS,Sw,Pow,900V,5A,120W,<3,6Ω(5A)	18c$	Sanyo	2SK727,2SK794,2SK1649..50,2SK1760..
2SK1462	MOS-N-FET-e	V-MOS,Sw,Pow,900V,8A,150W,<1,6Ω(5A)	18c$	Sanyo	2SK1358,2SK1502,2SK1614,2SK1795..

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2SK1463	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 4,5A, 60W, <3,6Ω(5A)	18c	Sanyo	2SK1684, 2SK1859
2SK1464	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 8A, 80W, <1,6Ω(5A)	18c	Sanyo	2SK1685..86, 2SK1775
2SK1465	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 8A, 200W, <1,6Ω(5A)	77c$	Sanyo	2SK1489
2SK1466	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 16A, 250W, <0,8Ω(5A)	77c$	Sanyo	-
2SK1467	MOS-N-FET-e*	LogL, V-MOS, Sw, 30V, 2A, <0,3Ω(5A)	39b	Sanyo	2SK1311, 2SK1470, 2SK1717
2SK1468	MOS-N-FET-e*	V-MOS, LogL, 30V, 4A, 20W, <0,12Ω(5A)	30c$	Sanyo	2SK1112, 2SK1471, 2SK1719
2SK1469	MOS-N-FET-e*	V-MOS, LogL, 30V, 8A, 30W, <0,055Ω(5A)	30c$	Sanyo	2SK1472, 2SK1748
2SK147	N-FET	GenP, LN, 40V, Idss>5mA, Up<1,2V	7a(9mm)	Tos	2N5247, 2SK130, 2SK151, 2SK162, 2SK363
2SK1470	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,45Ω(5A)	39b	Sanyo	2SK1311, 2SK1717, 2SK1763
2SK1471	MOS-N-FET-e*	V-MOS, LogL, 60V, 4A, 20W, <0,2Ω(5A)	30c$	Sanyo	2SK1112, 2SK1474, 2SK1719
2SK1472	MOS-N-FET-e*	V-MOS, LogL, 60V, 8A, 30W, <0,08Ω(5A)	30c$	Sanyo	2SK1475, 2SK1748
2SK1473	MOS-N-FET-e*	V-MOS, LogL, 100V, 2A, <0,95Ω(5A)	39b	Sanyo	2SK2055
2SK1474	MOS-N-FET-e*	V-MOS, LogL, 100V, 4A, 20W, <0,4Ω(5A)	30c$	Sanyo	2SK1804
2SK1475	MOS-N-FET-e*	V-MOS, LogL, 100V, 8A, 30W, <0,16Ω(5A)	30c$	Sanyo	2SK1557
2SK1476	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 12A, 150W, <0,65Ω(5A)	?18c$	Mit	2SK896, 2SK1488, 2SK1752, 2SK1785..
2SK1477	MOS-N-FET-e	=2SK1476: 500V, <0,78Ω(5A)	?18c$	Mit	2SK896, 2SK1488, 2SK1753, 2SK1785..
2SK1478	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, ±8A, 40W, <0,6Ω(5A)	17c	Matsushita	2SK526, 2SK1036, 2SK1568..69
2SK1479	N-FET	Imped.-Conv., 25V, 5mA, Idss>0,3mA	35f	Hit	-
2SK1479-A	N-FET	-	35	Hit	→2SK1479
2SK1479-B	N-FET	-	35	Hit	→2SK1479
2SK148	N-FET	FM/VHF, 25V, Idss<12mA	9e	Mat	-
2SK1480	MOS-N-FET-d	FM/VHF, 20V, ±30mA, Idss>1mA, Up<2V	35e	Nec	-
2SK1482	MOS-N-FET-e*	V-MOS, 30V, ±1,5A, 0,75W, <0,4Ω(0,5A)	7b	Nec	2SK1272, 2SK1733
2SK1483	MOS-N-FET-e*	-	39	Nec	→2SK1483
2SK1484	MOS-N-FET-e*	V-MOS, LogL, 100V, ±0,5A, 0,75W, <0,8Ω	7b	Nec	2SK1729
2SK1485	MOS-N-FET-e*	-	39	Nec	→2SK1485
2SK1486	MOS-N-FET-e	V-MOS, 300V, 32A, 200W, <0,095Ω(10A)	77c$	Tos	2SK1454, 2SK1628, 2SK1681
2SK1487	MOS-N-FET-e	V-MOS, 450V, 10A, 125W, <1Ω(5A)	18c$	Tos	2SK896, 2SK1488, 2SK1723, 2SK1752..
2SK1488	MOS-N-FET-e	V-MOS, 500V, 10A, 125W, <1Ω(5A)	18c$	Tos	2SK896, 2SK1723, 2SK1753, 2SK1785..
2SK1489	MOS-N-FET-e	V-MOS, 1000V, 12A, 200W, <1Ω(5A)	77c$	Tos	-
2SK149	N-FET	UHF, 20V, Idss>8mA, Up<2,2V	5m+	Nec	-
2SK1491	MOS-N-FET-e*	V-MOS, Sw, Pow, 250V, ±25A, 120W, <0,15Ω(10A)	18c$	Nec	2SK901, 2SK944, 2SK1641, 2SK1673..74
2SK1492	MOS-N-FET-e*	V-MOS, Sw, Pow, 250V, ±35A, 140W, <0,1Ω(10A)	18c$	Nec	2SK902, 2SK1669, 2SK1671, 2SK1675..76
2SK1493	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±3A, 50W, <2,8Ω(5A)	17c$	Nec	2SK1154, 2SK1244, 2SK1439
2SK1493..1494Z	MOS-N-FET-e*	=2SK1493..1494:	30c$	-	2SK2356Z
2SK1493..1496Z	MOS-N-FET-e*	=2SK1493..1496:	30c$	-	2SK1540..41
2SK1494	MOS-N-FET-e*	=2SK1493: 500V, <3Ω(5A)	17c$	Nec	2SK1154, 2SK1244
2SK1495	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±7A, 70W, <0,9Ω(5A)	17c$	Nec	IRF840, IRF842, 2SK1574
2SK1496	MOS-N-FET-e*	=2SK1495: 500V, <1Ω(5A)	17c$	Nec	IRF840, IRF842, 2SK1574
2SK1497	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±20A, 120W, <0,35Ω(10A)	18c$	Nec	2SK1169 .70, 2SK1409, 2SK1411, 2SK1680
2SK1498	MOS-N-FET-e*	=2SK1497: 500V, <0,4Ω(10A)	18c$	Nec	2SK1170, 2SK1411, 2SK1680
2SK1499	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±25A, 160W, <0,25Ω(10A)	18c$	Nec	2SK1169..70, 2SK1409, 2SK1411, 2SK1680
2SK15	N-FET	GenP, LN, 20V, Idss=0,45..5mA, Up<5V	5g	Tos	BFS70, 2N3821, 2N4220, 2SK104..
2SK150	N-FET	Dual, 50V, Idss>1mA, Up<2V	7-SIP/bp1	Tos	-
2SK1500	MOS-N-FET-e*	=2SK1499: 500V, <0,27Ω(10A)	18c$	Nec	2SK1170, 2SK1411, 2SK1680
2SK1501	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±4A, 70W, <4Ω(5A)	17c$	Nec	2SK1119, 2SK1457, 2SK1639, 2SK1643
2SK1501Z	MOS-N-FET-e	=2SK1501:	30c$	-	2SK1528
2SK1502	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±7A, 120W, <2Ω(5A)	18c$	Nec	2SK1358, 2SK1614, 2SK1692, 2SK1795
2SK1503(-01)	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 80W, <0,9Ω(5A)	17c$	Fjd	2SK2186, 2SK2366
2SK1504(-01)L,S	MOS-N-FET-e	=2SK1503:	30c$	Fjd	2SK2366Z
2SK1505	MOS-N-FET-e	V-MOS, 30V, 35A, 40W, <0,022e(17,5A)	?15c	Fjd	2SK1653, 2SK2120, 2SK2312, 2SK2529, +
2SK1505-MR	MOS-N-FET-e	V-MOS, 30V, 35A, 40W, <0,022e(17,5A)	17c	Fjd	2SK1653, 2SK2120, 2SK2312, 2SK2529, +
2SK1506	MOS-N-FET-e	V-MOS, 120V, 50A, 150W, <0,03Ω(20A)	18c$	Fjd	-
2SK1507(-01MR)	MOS-N-FET-e	V-MOS, 600V, 9A, 50W, <1Ω(5A)	17c	Fjd	-
2SK1508	MOS-N-FET-e	V-MOS, LogL, 60V, 35A, 60W, <56mΩ	17c$	Fjd	BUK555-60, 2SK1291, 2SK1296, 2SK2411...
2SK1509	MOS-N-FET-e	V-MOS, 100V, 20A, 60W, <80mΩ(10A)	17c$	Fjd	BUZ21, IRF540, IRF542, 2SK1116,..
2SK151	N-FET	AF, Sw, LN, 40V, Idss>6mA, Up<1,1V	7a(9mm)	Hit	2N5247
2SK1510(-01)L,S	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3,5A, 60W, <5,5Ω(5A)	30c$	Fjd	2SK1528, 2SK1659
2SK1511	MOS-N-FET-e	V-MOS, 1000V, 5A, 100W, <3Ω	18c$	Fjd	BUZ357..358, 2SK1205, 2SK1359, 2SK1773+
2SK1512	MOS-N-FET-e	V-MOS, 900V, 10A, 150W, <1,2Ω	18c$	Fjd	-
2SK1513	MOS-N-FET-e	V-MOS, 500V, ±8A, 150W, <0,75Ω(5A)	77c$	Tos	2SK1029
2SK1514	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 125W, <0,03Ω(20A)	18c$	Hit	2SK1297, 2SK1665
2SK1515	MOS-N-FET-e*	FREDFET, 450V, 10A, 100W, <0,8Ω(5A)	18c$	Hit	BUK637-450, 2SK683
2SK1516	MOS-N-FET-e*	=2SK1515: 500V, <0,9e(5A)	18c$	Hit	BUK637-500, 2SK683

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2SK1517	MOS-N-FET-e*	FREDFET,450V,20A,120W,<0,25Ω(10A)	18c$	Hit	-
2SK1518	MOS-N-FET-e*	=2SK1517:500V,<0,27Ω(10A)	18c$	Hit	-
2SK1519	MOS-N-FET-e*	FREDFET,450V,30A,200W,<0,15Ω(10A)	77c$	Hit	-
2SK152	N-FET	FM/VHF,15V,Idss>9,5mA,Up<2V	7d	Son	BF410D
2SK1520	MOS-N-FET-e*	=2SK1519:500V,<0,16Ω(10A)	77c$	Hit	-
2SK1521	MOS-N-FET-e*	FREDFET,450V,50A,250W,<0,1Ω(20A)	77c$	Hit	-
2SK1522	MOS-N-FET-e*	=2SK1521:500V,<0,11Ω(20A)	77c$	Hit	-
2SK1523	MOS-N-FET-e	=2SK1248:Iso	18c	Shi	2SK1206
2SK1524	MOS-N-FET-e	=2SK1249:Iso	18c	Shi	2SK1269,2SK1331,2SK1405
2SK1525	MOS-N-FET-e	=2SK1250:Iso	18c	Shi	2SK1406
2SK1526	MOS-N-FET-e*	V-MOS,450V,40A,250W,<0,15Ω(20A)	77c$	Hit	2SK1521..22
2SK1527	MOS-N-FET-e*	=2SK1526:500V,<0,16Ω(20A)	77c$	Hit	2SK1522
2SK1528(L,S)	MOS-N-FET-e*	V-MOS,900V,4A,60W,<4Ω(5A)	30c$	Hit	2SK1501Z,2SK2006
2SK1529	MOS-N-FET-e	V-MOS,AF-Pow,180V,10A,120W	18c$	Tos	-
2SK1530	MOS-N-FET-e	V-MOS,AF-Pow,200V,12A,150W	77c$	Tos	-
2SK1531	MOS-N-FET-e	V-MOS,500V,15A,150W,0,45Ω(5A)	18c$	Tos	2SK725,2SK788,2SK899,2SK1745,2SK1678
2SK1532	N-FET	=2SK1031:	35f(2mm)	Hit	-
2SK1532-B	N-FET	-	35(2mm)	Hit	→2SK1532
2SK1532-C	N-FET	-	35(2mm)	Hit	→2SK1532
2SK1532-D	N-FET	-	35(2mm)	Hit	→2SK1532
2SK1533	MOS-N-FET-e	V-MOS,900V,1A,10W,<15Ω,40/85nS	30c$	Shi	2SK2663,2SK3301
2SK1534	MOS-N-FET-e	V-MOS,900,3A,50W,<5Ω,45/110nS	17c$	Shi	2SK791..792,2SK1456,2SK1601,2SK1638..
2SK1535	MOS-N-FET-e	=2SK1534:Iso,30W	15c	Shi	2SK1356,2SK1460
2SK1536	MOS-N-FET-e	V-MOS,900V,3A,70W,<5Ω,45/110nS	16c$	Shi	2SK726,2SK1339
2SK1537	MOS-N-FET-e	V-MOS,900V,5A,100W,<3Ω,65/145nS	16c$	Shi	2SK727,2SK794,2SK1649..50,2SK1794..
2SK1538	MOS-N-FET-e	V-MOS,900V,7A,130W,<2Ω,80/200nS	16c$	Shi	2SK1342,2SK1358,2SK1462,2SK1795..
2SK1539	MOS-N-FET-e	V-MOS,900V,10A,150W,<1,4Ω,115/290nS	16c$	Shi	2SK1796
2SK154	N-FET	FM/VHF,20V,Idss<18mA	7f	Mat	-
2SK1540(L,S)	MOS-N-FET-e*	V-MOS,450V,7A,60W,<0,8Ω(5A)	30c$	Hit	2SK1315..16,2SK1495..96Z,2SK2359..60Z
2SK1541(L,S)	MOS-N-FET-e	=2SK1540:500V,<0,9e(5A)	30c$	Hit	2SK1316,2SK2187
2SK1542	MOS-N-FET-e	V-MOS,LogL,60V,45A,125W,<0,02Ω(20A)	17c$	Tos	BUK556-60,2SK1911
2SK1544	MOS-N-FET-e	V-MOS,500V,25A,200W,<0,2Ω(10A)	77c$	Tos	2SK1629,2SK1971
2SK1545	MOS-N-FET-e	V-MOS,800V,3A,40W,<6e	17c	Fjd	2SK1356,2SK1460,2SK1995
2SK1546	MOS-N-FET-e	V-MOS,900V,2,5A,40W,<7,3Ω	17c	Fjd	2SK1174,2SK1459,2SK1994
2SK1547(-01MR)	MOS-N-FET-e	V-MOS,800V,4A,40W,<4,5Ω(5A)	17c	Fjd	2SK1404,2SK1637,2SK2044..45,2SK2118..
2SK1548(-01MR)	MOS-N-FET-e	V-MOS,900V,3,5A,40W,<5,5Ω(5A)	17c	Fjd	2SK1356,2SK1460,2SK1995
2SK1549(-R)	MOS-N-FET-e	V-MOS,250V,20A,80W,<0,15Ω(10A)	18c	Fjd	2SK822,2SK2008
2SK155	N-FET	GenP,LN,20V,Idss>0,5mA,Up<1,5V	7a	Mat	2SK68,2SK106,2SK184
2SK1550	MOS-N-FET-e	V-MOS,600V,4A,40W,<1,8Ω	-	Fjd	-
2SK1552(-01)L,S	MOS-N-FET-e	V-MOS,800V,4A,60W,<4,5Ω(5A)	30c$	Fjd	2SK1528,2SK2006,2SK2089
2SK1553(-01MR)	MOS-N-FET-e	V-MOS,650V,5A,40W,<2,5Ω(2,5A)	17c	Fujitsu	2SK1404,2SK1637,2SK2118
2SK1554	MOS-N-FET-e	V-MOS,650V,3A,30W,<4,5Ω	17c	Fujitsu	2SK1572,2SK1767,2SK1995,2SK2144..
2SK1555	MOS-N-FET-e	V-MOS,LogL,50V,16A,75W,<0,05Ω(5A)	17c$	Mit	BUK552-50,2SK971
2SK1555S	MOS-N-FET-e	=2SK1555:	30c$	-	2SK1648,2SK1898,2SK2322
2SK1556	MOS-N-FET-e	V-MOS,Sw,Pow,100V,8A,30W,<0,2Ω(5A)	17c	Mitsubishi	BUK543-100,2SK1261
2SK1557	MOS-N-FET-e	=2SK1556:45W	30c$	Mit	2SK1475
2SK1558	MOS-N-FET-e	V-MOS,LogL,100V,15A,40W,<0,09Ω(5A)	17c	Mit	2SK1034,2SK1288,2SK1306
2SK1559	MOS-N-FET-e	=2SK1558:75W	17c$	Mit	2SK1301,2SK1561
2SK1559S	MOS-N-FET-e	=2SK1558:	30c$	-	-
2SK156	N-FET	AF-Pre,20V,Idss>0,06mA	41e	Sanyo	-
2SK1560	MOS-N-FET-e	V-MOS,LogL,150V,7A,45W,<0,3Ω(5A)	30c$	Mit	-
2SK1561	MOS-N-FET-e	V-MOS,LogL,150V,16A,75W,<0,12Ω(8A	17c$	Mit	BUK555-200
2SK1561S	MOS-N-FET-e	=2SK1561:	30c$	-	-
2SK1562	MOS-N-FET-e	V-MOS,Sw,Pow,450V,12A,150W,<0,65Ω(5A)	17c$	Mit	-
2SK1562..1563S	MOS-N-FET-e	=2SK1562..1563:	30c$	-	-
2SK1563	MOS-N-FET-e	=2SK1562:500V,<0,78Ω(5A)	17c$	Mit	-
2SK1564	MOS-N-FET-e	V-MOS,Sw,Pow,800V,3A,150W,<3,6Ω(1,5A)	17c$	Mit	-
2SK1564..1565S	MOS-N-FET-e	=2SK1564..1565:	30c$	-	-
2SK1565	MOS-N-FET-e	=2SK1564:900V,<4Ω(1,5A)	17c$	Mit	-
2SK1566	MOS-N-FET-e	=2SK1157:Iso,35W	17c	Hit	2SK1352,2SK1609,2SK1805
2SK1567	MOS-N-FET-e	=2SK1158:Iso,35W	17c	Hit	2SK1352,2SK1609,2SK1805
2SK1568	MOS-N-FET-e	V-MOS,Sw,Pow,250V,8A,40W,<0,6Ω(5A)	17c	Mitsubishi	2SK1478,2SK1668
2SK1569	MOS-N-FET-e	=2SK1468:300V,<0,65Ω(5A)	17c	Mit	-
2SK157	N-FET	50V,Idss>0,5mA,Up<1,5V	35f	Hit	2SK94

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2SK1570	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 12A, 150W, <0,78Ω(5A)	?18c$	Mit	2SK683, 2SK1488, 2SK1516, 2SK1785..
2SK1571	MOS-N-FET-e	=2SK1570: 500V, <0,9e(5A)	?18c$	Mit	2SK683, 2SK1488, 2SK1516, 2SK1785..
2SK1572	MOS-N-FET-e*	V-MOS, 600V, 3A, 25W, <5Ω(5A), 33/95nS	17c	Hit	2SK1767, 2SK2144
2SK1573	MOS-N-FET-e*	V-MOS, 600V, 15A, 125W, <0,5Ω(5A)	18c$	Hit	2SK2915
2SK1574	MOS-N-FET-e	V-MOS, 500V, 8A, 125W, <0,85Ω(5A)	17c$	Tos	IRF840, 2SK894, 2SK1496, 2SK2360
2SK1575	MOS-N-FET-e*	V-MOS, Dual, 180V, 16A, Pq>180W(190MHz)	-	Hit	-
2SK1576	N-FET	AF/HF, 30V, Idss=2,5..14mA, Up<1,5V	35f	Son	-
2SK1577	N-FET	VHF/UHF, 35V, Idss>30mA, Up<6V	35f	Son	-
2SK1577-1	N-FET	-	35	Son	→2SK1577
2SK1577-2	N-FET	-	35	Son	→2SK1577
2SK1577-3	N-FET	-	35	Son	→2SK1577
2SK1578	N-FET	Microphone Amplifier, 20V, 10mA, Idss>0,1mA, Up<1,5V	40e	Sanyo	-
2SK1579	MOS-N-FET-e*	V-MOS, Rgate, 12V, ±2A, 500/1500nS	39b	Hit	-
2SK158	N-FET	55V, Idss<6,5mA	35b	Mat	-
2SK1580	MOS-N-FET-e*	V-MOS, LogL, 16V, ±0,1A, <10Ω(10A)	35a(2mm)	Nec	-
2SK1581	MOS-N-FET-e*	V-MOS, LogL, 16V, ±0,2A, <3Ω(10A)	35a	Nec	BSS123, 2SK1590..91
2SK1582	MOS-N-FET-e*	V-MOS, LogL, 30V, ±0,2A, <3Ω(10mA)	35a	Nec	2SK1590..91, 2SK2731
2SK1583	MOS-N-FET-e*	V-MOS, LogL, 16V, ±0,5A, <1,5Ω	39b	Nec	2SK1592, 2SK1697, 2SK2109
2SK1584	MOS-N-FET-e*	V-MOS, LogL, 30V, ±0,5A, <1,5Ω	39b	Nec	2SK1592, 2SK1697, 2SK2109
2SK1585	MOS-N-FET-e*	V-MOS, LogL, 16V, ±1A<1Ω(0,5A)	39b	Nec	2SK1726, 2SK2111
2SK1586	MOS-N-FET-e*	V-MOS, LogL, 30V, ±1A<0,6Ω(0,5A)	39b	Nec	2SK1726, 2SK2111
2SK1587	MOS-N-FET-e*	V-MOS, LogL, 16V, ±2A, <0,5Ω(5A)	39b	Nec	2SK1311, 2SK1470, 2SK1717, 2SK2315
2SK1588	MOS-N-FET-e*	V-MOS, LogL, 16V, ±3A, <0,3Ω(5A)	39b	Nec	2SK2054
2SK1589	MOS-N-FET-e*	V-MOS, LogL, 100V, ±0,1A, <25Ω	35a	Nec	BSS123
2SK1590	MOS-N-FET-e*	V-MOS, LogL, 60V, ±0,2A, <3Ω	35a	Nec	2SK1849
2SK1591	MOS-N-FET-e*	V-MOS, LogL, 100V, ±0,2A, <6,5Ω	35a	Nec	2SK1849
2SK1592	MOS-N-FET-e*	V-MOS, LogL, 60V, ±0,5A, <2Ω(0,5A)	39b	Nec	2SK1697, 2SK2109..10
2SK1593	MOS-N-FET-e*	V-MOS, LogL, 100V, ±0,5A, <5Ω(0,5A)	39b	Nec	2SK1079, 2SK2110
2SK1594	MOS-N-FET-e*	V-MOS, LogL, 30V, ±20A, 30W, <45mΩ(10A)	17c	Nec	BUK545-50, 2SK943, 2SK1214, 2SK1345..46
2SK1595	MOS-N-FET-e*	V-MOS, LogL, 30V, ±30A, 35W, <0,03Ω(10A)	17c	Nec	2SK1262
2SK1596	MOS-N-FET-e*	V-MOS, LogL, 30V, ±40A, 35W, <0,02Ω(20A)	17c	Nec	2SK1257, 2SK1653, 2SK1952
2SK16	N-FET	GenP, LN, 15V, Idss=0,5..7mA, Up<5V	5a	Hit	BF570, 2N3821, 2N4220, 2SK104..
2SK160	N-FET	VHF, 30V, Idss>0,5mA, Up<4,5V	35f	Nec	-
2SK1600	MOS-N-FET-e	V-MOS, 800V, 3A, 75W, <5Ω(1,5A)	17c$	Tos	BUK456-800, 2SK1456, 2SK1638, 2SK2603
2SK1601	MOS-N-FET-e	=2SK1600: 900V, <6,4Ω(1,5A)	17c$	Tos	BUK456-1000, 2SK1456, 2SK1638
2SK1602	MOS-N-FET-e	=2SK1600: 2,8A, 40W	17c	Tos	2SK1356, 2SK1460
2SK1603	MOS-N-FET-e	=2SK1601: 2,5A, 40W	17c	Tos	2SK1356, 2SK1460, 2SK1995
2SK160-4	N-FET	-	35	Nec	→2SK160
2SK1605	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, ±5A, 50W, <1,3Ω(5A)	17c	Matsushita	2SK1231..32, 2SK1351, 2SK1626..27..
2SK160-5	N-FET	-	35	Nec	→2SK160
2SK1606	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, ±8A, 50W, <0,75Ω(5A)	17c	Matsushita	2SK1352, 2SK1566..1567
2SK160-6	N-FET	-	35	Nec	→2SK160
2SK1607	MOS-N-FET-e	V-MOS, 450V, ±13A, 120W, <0,45Ω(5A)	18c$	Mat	BUZ338, 2SK725, 2SK788, 2SK899, 2SK1745
2SK160-7	N-FET	-	35	Nec	→2SK160
2SK1608	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, ±5A, 50W, <1,7Ω(5A)	17c	Matsushita	2SK1232, 2SK1351, 2SK1627, 2SK2236..
2SK1609	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, ±8A, 50W, <1Ω(5A)	17c	Matsushita	2SK1352, 2SK1567, 2SK1805, 2SK2117..
2SK160A	N-FET	=2SK160: 50V	35f	-	-
2SK160A-K24	N-FET	-	35	Nec	→2SK160A
2SK160A-K25	N-FET	-	35	Nec	→2SK160A
2SK160A-K26	N-FET	-	35	Nec	→2SK160A
2SK160A-K27	N-FET	-	35	Nec	→2SK160A
2SK161	N-FET	FM/VHF, 18V, Idss>1mA, Up<4V	41d	Tos	2N5246, 2SK107
2SK1610	MOS-N-FET-e	V-MOS, 500V, n13A, 120W, <0,6Ω(5A)	18c$	Mat	BUZ338, 2SK725, 2SK788, 2SK899, 2SK1757
2SK1611	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, ±3A, 50W, <4Ω(5A)	17c	Matsushita	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK1612	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±3A, 50W, <5Ω(5A)	17c	Matsushita	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK1613	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±5A, 120W, <2,8Ω(5A)	18c$	Mat	2SK685, 2SK727, 2SK1461, 2SK1649..50..
2SK1614	MOS-N-FET-e	V-MOS, 900V, ±8A, 120W, <1,7Ω(5A)	18c$	Mat	2SK1120, 2SK1358, 2SK1502, 2SK1692..
2SK1615	GaAs-N-FET	SHF, 3,5V, 60mA, Idss=12..60mA, 12GHz	51y	Hit	-
2SK1616	GaAs-N-FET	SHF, 3,5V, 70mA, Idss=12..70mA, 12GHz	52y	Hit	-
2SK1617	GaAs-N-FET	SHF, 3,5V, 60mA, Idss=12..60mA, 12GHz	52y	Hit	-
2SK1618	MOS-N-FET-e*	V-MOS, 600V, 3A, 30W, <5Ω(5A)	30c$	Hit	2SK1624
2SK1619	GaAs-N-FET	UHF, 3V, 0,06A, Idss=15..60mA, 12GHz	52y	Hit	-
2SK162	N-FET	GenP, LN, 40V, Idss>5mA, Up<1,2V	7a	Nec	2SK147, 2SK151
2SK1620(L,S)	MOS-N-FET-e*	V-MOS, 150V, 10A, 50W, <0,15Ω(5A)	30c$	Hit	2SK1636, 2SK1741

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2SK1621(L,S)	MOS-N-FET-e*	V-MOS, 250V, 7A, 50W, <0,55Ω(5A)	30c$	Hit	2SK1636
2SK1622(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <0,04Ω(10A)	30c$	Hit	2SK1918, 2SK2311
2SK1623(L,S)	MOS-N-FET-e*	V-MOS, 100V, 20A, 50W, <0,085Ω(10A)	30c$	Hit	-
2SK1624(L,S)	MOS-N-FET-e*	V-MOS, 600V, 4A, 50W, <2,4Ω(5A)	30c$	Hit	-
2SK1625(L,S)	MOS-N-FET-e*	V-MOS, 600V, 7A, 75W, <1,3Ω(5A)	30c$	Hit	SSW6N60A, 2SK2060, 2SK2140Z, 2SK2908
2SK1626	MOS-N-FET-e*	=2SK1155: Iso, 35W	17c	Hit	2SK1231..32, 2SK1351, 2SK1608
2SK1627	MOS-N-FET-e*	=2SK1156: Iso, 35W	17c	Hit	2SK1232, 2SK1351, 2SK1608
2SK1628	MOS-N-FET-e*	V-MOS, 450V, 30A, 200W, <0,25Ω(10A)	77c$	Hit	2SK1454, 2SK1519..20, 2SK1681, 2SK1629
2SK1629	MOS-N-FET-e*	=2SK1628: 500V, <0,27Ω(10A)	77c$	Hit	2SK1520
2SK163	N-FET	GenP, LN, 50V, Idss>1mA, Up<1,2V	7a	Nec	2SK43, 2SK121, 2SK170, 2SK186..187,..
2SK1630	MOS-N-FET-e	V-MOS, Sw, Pow, 700V, 3A, 75W, <4,4Ω(5A)	17c$	Mit	2SK1456, 2SK1600..01, 2SK1638, 2SK1793..
2SK1631	MOS-N-FET-e	=2SK1630: Iso, 35W	17c	Mit	2SK1356, 2SK1460, 2SK1995
2SK1632	MOS-N-FET-e	V-MOS, Sw, Pow, 700V, 5A, 100W, <2,3Ω(5A)	17c$	Mit	2SK1457, 2SK1501, 2SK1639, 2SK1643..
2SK1632S	MOS-N-FET-e	=2SK1632:	30c$	-	-
2SK1633	MOS-N-FET-e	=2SK1632: Iso, 45W	17c	Mit	2SK1808, 2SK1985
2SK1634	MOS-N-FET-e	=2SK1632: 150W	?18c$	Mit	2SK1341, 2SK1461, 2SK1760, 2SK1794
2SK1635	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 50A, 130W, <23mΩ(20A)	77c$	Mat	2SK1223, 2SK1380
2SK1636(L,S)	MOS-N-FET-e*	V-MOS, 250V, 15A, 75W, <0,27Ω(5A)	30c$	Hit	2SK2063, 2SK2133Z, 2SK2254
2SK1637	MOS-N-FET-e*	V-MOS, 600V, 4A, 35W, <2,4Ω(5A)	17c	Hit	2SK1118, 2SK1404
2SK1638	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 60W, <5,5Ω(5A)	17c$	Hit	BUK456-1000, 2SK1456, 2SK1601, 2SK1793
2SK1639	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 4A, 75W, <4Ω(5A)	17c$	Hit	2SK1119, 2SK1501, 2SK1639, 2SK1643
2SK1641	MOS-N-FET-e	V-MOS, 250V, 20A, 150W, <0,23Ω(10A)	18c$	Tos	2SK623, 2SK901, 2SK944, 2SK1673..74
2SK1642	MOS-N-FET-e	V-MOS, 400V, 9A, 45W, <0,55Ω(5A)	17c	Tos	2SK1446..47, 2SK1609, 2SK2116..17..
2SK1643	MOS-N-FET-e	V-MOS, 900V, 5A, 125W, <2,8Ω(5A)	17c$	Tos	2SK1639, 2SK1501
2SK1646	GaAs-N-FET-d	SHF, 6V, 100mA, Idss>15mA, 12GHz	44	Sanyo	-
2SK1647(L,S)	MOS-N-FET-e*	V-MOS, 900V, 2A, 50W, <7Ω(5A)	30c$	Hit	2SK2005
2SK1648(L,S)	MOS-N-FET-e*	V-MOS, 60V, 15A, 40W, <0,065Ω(5A)	30c$	Hit	2SK1622, 2SK1918, 2SK2284
2SK1649	MOS-N-FET-e	V-MOS, 900V, 6A, 150W, <2,5Ω(5A)	18c$	Tos	2SK1358, 2SK1502, 2SK1614, 2SK1795,..
2SK165	N-FET	Video-Camera, 15V, Idss>8mA, Up<3V	7e,7d	Mat	-
2SK1650	MOS-N-FET-e	V-MOS, 900V, 4A, 125W, <4,3Ω(1,5A)	18c$	Tos	2SK727, 2SK794, 2SK1461, 2SK1760,..
2SK1651	MOS-N-FET-e	V-MOS, 500V, 8A, 80W, <1Ω(5A)	16c	Tos	2SK1206, 2SK1329, 2SK1696, 2SK1832
2SK1653	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 45W, <0,02Ω(20A)	17c	Toshiba	2SK1257, 2SK1952, 2SK2120, 2SK2312
2SK1654	MOS-N-FET	250V, 16A	17c$	Mit	-
2SK1655	MOS-N-FET	300V, 16A	17c$	Mit	-
2SK1656	MOS-N-FET-e*	V-MOS, LogL, 30V, ±0,1A, 0,25W, <25Ω	40c	Nec	BS170, BSS98 2SK1336
2SK1657	MOS-N-FET-e*	-	35	Nec	→2SK1657
2SK1658	MOS-N-FET-e*	-	35(2mm)	Nec	→2SK1658
2SK1659(L,S)	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 80W, <5Ω(1,5A)	30c$	Fjd	2SK1528
2SK1660	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,65e	18c	Fjd	2SK1452, 2SK1523, 2SK1696, 2SK1831..32..
2SK1661	MOS-N-FET-e	V-MOS, 200V, 20A, 80W, <0,17Ω	30c$	Fjd	2SK2107
2SK1662	MOS-N-FET-e	V-MOS, 700V, 3A, 40W, <5,5Ω	17c	Fujitsu	2SK1356, 2SK1460, 2SK1995
2SK1663(L,S)	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 80W, <4Ω(1,5A)	30c$	Fjd	2SK1510, 2SK1528
2SK1664	MOS-N-FET-e	V-MOS, Sw, Pow, 700V, ±2A, 30W, <6Ω(5A)	17c	NEC	BUK446-800, 2SK1142, 2SK1611, 2SK1834
2SK1665	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 125W, <0,02Ω(20A)	18c$	Hit	BUK539-60, 2SK1379, 2SK1297, 2SK1514
2SK1666	MOS-N-FET-e	=2SK1665: Iso, 60W	?18c	Hit	2SK1298, 2SK1653
2SK1667	MOS-N-FET-e*	V-MOS, 250V, 7A, 50W, <0,55Ω(5A)	17c$	Hit	2SK741, 2SK1319..20, 2SK1400
2SK1668	MOS-N-FET-e*	=2SK1667: Iso	17c	Hit	2SK1478, 2SK1568..69
2SK1669	MOS-N-FET-e*	FREDFET, 250V, 30A, 125W, <0,095Ω(10A)	18c$	Hit	-
2SK1670	MOS-N-FET-e*	=2SK1669: Iso, 60W	?18c	Hit	-
2SK1671	MOS-N-FET-e*	V-MOS, 250V, 30A, 125W, <0,095Ω(10A)	18c$	Hit	2SK902, 2SK1675..76
2SK1672	MOS-N-FET-e	V-MOS, 500V, 1A, 10W, <7Ω, 40/65nS	30c$	Shi	2SK580, 2SK1152, 2SK1327, 2SK2017
2SK1673	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 24A, 200W, <0,17Ω(10A)	?18c$	Mit	-
2SK1674	MOS-N-FET-e	=2SK1673: 300V, <0,2Ω(10A)	?18c$	Mit	-
2SK1675	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 30A, 250W, <0,13Ω(10A)	?18c$	Mit	-
2SK1676	MOS-N-FET-e	=2SK1675: 300V, <0,15Ω(10A)	?18c$	Mit	-
2SK1677	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 16A, 200W, <0,39Ω(5A)	?18c$	Mit	2SK1409, 2SK1411
2SK1678	MOS-N-FET-e	=2SK1677: 500V, <0,47Ω(5A)	?18c$	Mit	2SK1411
2SK1679	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 20A, 250W, <0,3Ω(10A)	?18c$	Mit	2SK1409, 2SK1411
2SK168	N-FET	FM-Preamp/Mix/Osc, 30V, Idss>4mA, Up<3V	7f	Hit	BF410C
2SK1680	MOS-N-FET-e	=2SK1679: 500V, <0,35Ω(10A)	?18c$	Mit	2SK1411
2SK1681	MOS-N-FET-e	V-MOS, 500V, 30A, 300W, <0,23Ω(10A)	77c$	Shi	2SK1520, 2SK1629, 2SK1971
2SK1682	N-FET	AM/FM, 30V, Idss=1..12mA, Up<4V	35f	Son	2SK374
2SK1683	MOS-N-FET-e	=2SK1536: Iso, 50W	18c	Shi	2SK1463
2SK1684	MOS-N-FET-e	=2SK1537: Iso, 55W	18c	Shi	2SK1463

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2SK1685	MOS-N-FET-e	=2SK1538:Iso,65W	18c	Shi	2SK1464,2SK1775
2SK1686	MOS-N-FET-e	=2SK1539:Iso,70W	18c	Shi	-
2SK1687	GaAs-N-FET	UHF,X..Ku-Band,4V,60mA,12GHz	51y	Mat	-
2SK1688	GaAs-N-FET	UHF,X..Ku-Band,4V,60mA,12GHz	51y	Mat	-
2SK1689	GaAs-N-FET	UHF,X..Ku-Band,6V,70mA,12GHz	51y	Mat	-
2SK169	N-FET	AF,LN,15V,50mA,Idss<50mA	7	Mat	-
2SK1690	MOS-N-FET-e	V-MOS,Sw,Pow,450V,3A,50W,<2,6Ω(1,5A)	30c$	Sanyo	2SK1691
2SK1691	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,60W,<1,4Ω(5A)	30c$	Sanyo	2SK1313..14,2SK1722,2SK1750Z
2SK1692	MOS-N-FET-e	V-MOS,900V,7A,150W,<2Ω(3,5A)	18c$	Tos	2SK1342,2SK1358,2SK1614,2SK1795..
2SK1693	MOS-N-FET-e	V-MOS,500V,8A,60W,<0,85e,60/120nS	17c$	Shi	IRF840,IRF842,2SK1496,2SK1574..
2SK1694	MOS-N-FET-e	=2SK1693:Iso,35W	15c	Shi	2SK1352,2SK1567,2SK1609,2SK1805,..
2SK1695	MOS-N-FET-e	V-MOS,500V,10A,80W,<0,85e,60/120nS	16c$	Shi	2SK724,2SK896,2SK1488,2SK1753,..
2SK1696	MOS-N-FET-e	=2SK1695:Iso,50W	18c	Shi	2SK1206,2SK1329,2SK1523
2SK1697	MOS-N-FET-e*	V-MOS,LogL,60V,0,5A,<1,7Ω(0,5A)	39b	Hit	2SK1079
2SK1698	MOS-N-FET-e*	V-MOS,LogL,100V,0,3A,<4,5Ω(0,5A)	39b	Hit	2SK1079
2SK1699	MOS-N-FET-e	V-MOS,Sw,Pow,450V,5A,75W,<1,8Ω(5A)	17c$	Mit	BUZ41A..42,2SK893,2SK1246,2SK1751,..
2SK1699S	MOS-N-FET-e	=2SK1699:	30c$	-	-
2SK17	N-FET	GenP,LN,20V,Idss=0,3..6,5mA,Up<6V	7e	Tos	BFS70,2N3369,2N3821,2SK381..
2SK170	N-FET	GenP,LN,40V,Idss>1mA,Up<1,5V	7a	Tos	2SK43,2SK121,2SK163,2SK186..187..
2SK1700	MOS-N-FET-e	=2SK1699:Iso,35W	17c	Mit	2SK1231..32,2SK1351,2SK1608,2SK1626..
2SK1701	MOS-N-FET	450V,8A	17c$	Mit	-
2SK1702	MOS-N-FET	V-MOS,450V,8A	17c	Mit	2SK1352,2SK1566..67,2SK2116..17..
2SK1703	MOS-N-FET-e	V-MOS,Sw,Pow,500V,5A,75W,<2,4Ω(5A)	17c$	Mit	BUZ41A..42,2SK893,2SK1246,2SK1751,..
2SK1703S	MOS-N-FET-e	=2SK1703:	30c$	-	-
2SK1704	MOS-N-FET-e	=2SK1703:Iso,35W	17c	Mit	2SK1232,2SK1351,2SK1608,2SK1627,..
2SK1705	MOS-N-FET	500V,8A	17c$	Mit	-
2SK1706	MOS-N-FET	V-MOS,500V,8A	17c	Mit	2SK1352,2SK1566..67,2SK2116..17..
2SK1707	MOS-N-FET	600V,4A	17c$	Mit	-
2SK1708	MOS-N-FET	V-MOS,600V,4A	17c	Mit	2SK1404,2SK1637,2SK2044,2SK2118..
2SK1709	MOS-N-FET	600V,6A	17c$	Mit	-
2SK171	N-FET	Dual,20V,80mA,Idss>5mA,Up<2V	7-SIP/bp1	Mit	-
2SK1710	MOS-N-FET	V-MOS,600V,6A	17c	Mit	-
2SK1711	MOS-N-FET-e	V-MOS,LogL,60V,±10A,25W,<0,2Ω(5A)	17c	Sanken	2SK1033,2SK1093,2SK1256,2SK1895..
2SK1712	MOS-N-FET-e	V-MOS,LogL,60V,±15A,30W,<0,1Ω(5A)	17c	Sanken	2SK1094,2SK1286,2SK1896,2SK2285..
2SK1713	MOS-N-FET-e	V-MOS,LogL,60V,±22A,35W,<50mΩ(10A)	17c	Sanken	2SK1095,2SK1346,2SK1882,2SK2346..
2SK1714	MOS-N-FET-e	V-MOS,LogL,60V,±30A,40W,<28mΩ(10A)	17c	Sanken	2SK1421,2SK1653,2SK2120,2SK2529..
2SK1715	MOS-N-FET-e	V-MOS,LogL,60V,±40A,90W,<28mΩ(20A)	18c	Sak	2SK1298,2SK1424,2SK1660,2SK2203..
2SK1716	MOS-N-FET-e*	V-MOS,LogL,60V,2A,20W,<0,37Ω(5A)	?15c	Tos	BUK541-100,2SK1255
2SK1717	MOS-N-FET-e*	-	39	Mat	→2SK1717
2SK1718	MOS-N-FET-e*	V-MOS,LogL,60V,6A,25W,<0,11Ω(5A)	?15c	Tos	BUK541-60,BUK542-100,2SK1255,2SK1260
2SK1719	MOS-N-FET-e*	V-MOS,LogL,60V,5A,20W,<0,11Ω(2,5A)	30c$	Tos	2SK1112,2SK1804,2SK1949
2SK1720	MOS-N-FET-e	V-MOS,60V,45A,100W,<0,03Ω(20A)	30c$	Tos	2SK1792,2SK1919,2SK2164,2SK2266
2SK1721	MOS-N-FET-e	V-MOS,500V,3A,40W,<3Ω(5A),30/80nS	30c$	Tos	2SK1314,2SK1541,2SK2066,2SK2181,..
2SK1722	MOS-N-FET-e	V-MOS,500V,5A,60W,<1,5Ω(2,5A)	30c$	Tos	2SK1316,2SK2067,2SK2184
2SK1723	MOS-N-FET-e	V-MOS,600V,12A,150W,<0,65Ω(5A)	18c$	Tos	2SK1968
2SK1724	MOS-N-FET-e*	-	39	Sanyo	→2SK1724
2SK1725	MOS-N-FET-e*	V-MOS,LogL,30V,1A,1W,<0,75Ω(0,5A)	9c	Sanyo	2SK1727,2SK1733
2SK1726	MOS-N-FET-e*	-	39	Sanyo	→2SK1726
2SK1727	MOS-N-FET-e*	V-MOS,LogL,60V,0,8A,1W,<1,2Ω(0,5A)	9c	Sanyo	2SK1729,2SK1733
2SK1728	MOS-N-FET-e*	-	39	Sanyo	→2SK1728
2SK1729	MOS-N-FET-e*	V-MOS,LogL,100V,0,5A,<3,5Ω(0,25A)	9c	Sanyo	2SK2085
2SK173	MOS-N-FET-e	V-MOS,Pow,210V,10A,95W	23e*	Son	(BUZ35,2SK401)
2SK1730	MOS-N-FET-e*	V-MOS,LogL,30V,1,8A,1W,<0,3Ω(5A)	9c	Sanyo	2SK1470,2SK1717,2SK1733
2SK1731	MOS-N-FET-e*	V-MOS,LogL,30V,3A,<0,14Ω(1,5A)	?12b	Sanyo	2SK1735
2SK1732	MOS-N-FET-e*	V-MOS,LogL,30V,4,5A,<0,065Ω(2,5A)	?12b	Sanyo	2SK1735
2SK1733	MOS-N-FET-e*	V-MOS,LogL,60V,1,5A,<0,45Ω(0,7(A)	9c	Sanyo	2SK1736
2SK1734	MOS-N-FET-e*	V-MOS,LogL,60V,2,5A,<0,22Ω(1,5A)	?12b	Sanyo	2SK1738
2SK1735	MOS-N-FET-e*	V-MOS,LogL,60V,4A,<0,09Ω(5A)	?12b	Sanyo	-
2SK1736	MOS-N-FET-e*	V-MOS,LogL,100V,1A,<0,95Ω(0,5A)	9c	Sanyo	2SK2085
2SK1737	MOS-N-FET-e*	V-MOS,LogL,100V,1,8A,<0,4Ω(5A)	?12b	Sanyo	-
2SK1738	MOS-N-FET-e*	V-MOS,LogL,100V,3A,<0,17Ω(1,5A)	?12b	Sanyo	-
2SK1739(A)	MOS-N-FET-e	V-MOS,UHF-Pow,80V,11A,Pq=90W(770MHz)	-	Tos	-
2SK1740	N-FET	40V,0,1A,Idss=40..75mA,Up<5V	35e	Sanyo	-
2SK1741	MOS-N-FET-e	V-MOS,100V,10A,40W,<0,16Ω(5A)	30c$	Sanyo	2SK1620,2SK1636

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2SK1745	MOS-N-FET-e	V-MOS, 500V, 18A, 150W, <0,36Ω(5A)	18c$	Tos	2SK870, 2SK1170, 2SK1498, 2SK1500..
2SK1746	MOS-N-FET-e	V-MOS, 600V, 2A, 40W, <4Ω(5A), 23/80nS	30c$	Tos	2SK1624, 2SK1980
2SK1747	N-FET	Dual, 40V, Idss=40..75mA, Up<5V	-	Sanyo	-
2SK1748(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±8A, 20W, <0,11Ω(5A)	30c$	Nec	2SK1472, 2SK2415
2SK1749	MOS-N-FET-e	V-MOS, LogL, 60V, ±50A, 150W, <18mΩ(20A)	18c$	Sanyo	BUK539-60, 2SK1258, 2SK1379, 2SK2121
2SK175	MOS-N-FET-e	V-MOS, 180V, 8A, 125W, 250/90nS, <1,7Ω	23e*	Hit	2SK258, (BUZ33)
2SK1750	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±5A, 50W, <1,4Ω(2,5A)	17c$	Nec	BUZ41A..42, 2SK552..53, 2SK893, 2SK1246
2SK1750Z..1751Z	MOS-N-FET-e*	=2SK1750..51:	30c$	-	2SK2355Z..56Z
2SK1751	MOS-N-FET-e*	=2SK1750: 500V, <1,5Ω(2,5A)	17c$	Nec	BUZ41..42, 2SK553, 2SK893, 2SK1246..
2SK1752	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±10A, 100W, <0,9Ω(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1785..
2SK1753	MOS-N-FET-e*	=2SK1752: 500V, <1Ω(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1785..
2SK1754	MOS-N-FET-e	V-MOS, LogL, 50V, 10A, 45W, <0,09Ω(5A)	30c$	Mit	MTD12N06EZL, 2SK2018, 2SK2414
2SK1756	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±15A, 120W, <0,5Ω(5A)	18c$	Nec	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1757	MOS-N-FET-e*	=2SK1756: 500V, <0,6Ω(5A)	18c$	Nec	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1758	MOS-N-FET-e*	V-MOS, Sw, Pow, 600V, ±2A, 30W, <4,2Ω(5A)	17c	Nec	BUK445-600, 2SK1142, 2SK1834
2SK176	MOS-N-FET-e	=2SK175: 200V	23e*	Hit	2SK258, (BUZ33)
2SK1760	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±5A, 100W, <4Ω(5A)	18c$	Nec	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK1761	MOS-N-FET-e*	V-MOS, 250V, 12A, 75W, <0,35Ω(5A)	17c$	Hit	-
2SK1762	MOS-N-FET-e*	=2SK1761: Iso, 35W	17c	Hit	-
2SK1763(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 2,5A, 10W, <0,35Ω	30c$	Hit	2SK974, 2SK1282
2SK1764	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,45Ω(5A)	39b	Hit	2SK1311, 2SK1470, 2SK1717, 2SK2054..
2SK1766	MOS-N-FET-e	V-MOS, 250V, 10A, 40W, <0,6Ω(5A)	17c	Tos	2SK1036, 2SK1762, 2SK2011, 2SK2426
2SK1767	MOS-N-FET-e	V-MOS, 600V, 3,5A, 40W, <2,5Ω(2,5A)	17c	Hit	2SK1572, 2SK2144
2SK1768	MOS-N-FET-e	V-MOS, LogL, 60V, 12A, 15W, <0,07Ω(5A)	?30c$	Tos	-
2SK1769	MOS-N-FET-e	V-MOS, 600V, 2A, 15W, <4Ω(5A)	?30c$	Tos	-
2SK1770	MOS-N-FET-e	=2SK1205: Iso, 60W	?18c	Hit	-
2SK1771	MOS-N-FET-e	V-MOS, FM/VHF, 12,5V, 30mA	44(SD-G)	Tos	-
2SK1772	MOS-N-FET-e*	V-MOS, LogL, 30V, 1A, <0,6Ω(0,5A)	39b	Hit	2SK1485, 2SK1726, 2SK1728
2SK1773	MOS-N-FET-e*	V-MOS, 1000V, 5A, 100W, <2Ω(5A)	18c$	Hit	BUZ357..358, 2SK1120, 2SK1205, 2SK1359
2SK1774	MOS-N-FET-e	=2SK684: Iso, 60W	?18c	Hit	2SK1464, 2SK1685
2SK1775	MOS-N-FET-e*	=2SK1342: Iso, 60W	?18c	Hit	2SK1464, 2SK1685..86
2SK1776	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 20W, <0,15Ω(5A)	17c	Hit	-
2SK1777	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 25W, <65mΩ(5A)	17c	Hit	-
2SK1778	MOS-N-FET-e*	V-MOS, LogL, 80V, 10A, 25W, <25mΩ(5A)	17c	Hit	-
2SK1779	MOS-N-FET-e	V-MOS, 800V, 3A, 80W, <3,5e	30c$	Tos	2SK1510, 2SK1659
2SK1784	MOS-N-FET-e*	V-MOS, Sw, Pow, 450V, ±12A, 100W, <0,6Ω(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1723..
2SK1785	MOS-N-FET-e*	=2SK1784: 500V, <0,7Ω(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1723..
2SK1792	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <20mΩ(20A)	30c$	Tos	2SK1919, 2SK2164, 2SK2266, 2SK2376
2SK1793	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±3A, 75W, <7,5Ω(5A)	17c$	Nec	BUK456-1000, 2SK1456, 2SK1601, 2SK1638+
2SK1793Z	MOS-N-FET-e*	=2SK1793:	30c$	-	2SK1510
2SK1794	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±6A, 100W, <2,8Ω(5A)	18c$	Nec	2SK1358, 2SK1614, 2SK1502, 2SK1692..
2SK1795	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±8A, 140W, <1,6Ω(5A)	18c$	Nec	2SK1358, 2SK1614, 2SK1502, 2SK1692..
2SK1796	MOS-N-FET-e*	V-MOS, Sw, Pow, 900V, ±10A, 150W, <1,2Ω(5A)	18c$	Nec	2SK1933
2SK18	N-FET	Dual, Sw/VHF, 40V, Idss>0,45mA, Up<3,5V	81by	Tos	-
2SK180	MOS-N-FET-e	V-MOS, Pow, 600V, 20A, 300W, 200/250nS	68e*	old	-
2SK1803	MOS-N-FET-e	V-MOS, 900V, ±8A, 100W, <1,7Ω(5A)	18c(S)	Mat	2SK1358, 2SK1614, 2SK1502, 2SK1692..
2SK1804	MOS-N-FET-e*	V-MOS, LogL, 100V, 5A, 20W, <0,28Ω(2,5A)	30c$	Tos	2SK1474
2SK1805	MOS-N-FET-e	V-MOS, 500V, 7A, 45W, <0,85Ω(5A)	17c	Toshiba	2SK1352, 2SK1567, 2SK1609
2SK1806	N-FET	GeP, 30V, Idss=0,6..6mA, Up<2,5V	-	Sanyo	-
2SK1807	MOS-N-FET-e*	V-MOS, 900V, 4A, 60W, <4Ω(5A)	17c$	Tos	2SK1639, 2SK1643, 2SK1501
2SK1808	MOS-N-FET-e*	=2SK1807: Iso, 35W	17c	Tos	2SK1985
2SK1809	MOS-N-FET-e*	=2SK1404: 60W	17c$	Hit	2SK1117, 2SK1402
2SK181	MOS-N-FET-e	=2SK180: 800V	68e*	old	-
2SK1810	MOS-N-FET-e	V-MOS, 300V, 10A, 50W, <0,7Ω(5A)	17c$	Shi	BUZ61, 2SK1378
2SK1811	MOS-N-FET-e	V-MOS, 300V, 20A, 100W, <0,35Ω(10A)	16c$	Shi	2SK868, 2SK1674
2SK1812	MOS-N-FET-e	V-MOS, 300V, 30A, 120W, <0,23Ω(10A)	16c$	Shi	2SK1676
2SK1813	MOS-N-FET-e	V-MOS, 100V, 30A, 70W, <0,55Ω(20A)	30c$	Sanyo	-
2SK1814	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 20A, 45W, <70mΩ(10A)	17c$	Fjd	BUK555-60, 2SK972, 2SK1115, 2SK1296
2SK1815	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 35A, 50W, <35mΩ(17,5A)	18c	Fjd	2SK1424, 2SK1435..36, 2SK1666
2SK1816	MOS-N-FET-e	V-MOS, 100V, 5A, 20W	30c$	Fjd	-
2SK1817(-M)	MOS-N-FET-e	V-MOS, LogL, 100V, 20A, 40W, <0,12Ω	17c	Fjd	2SK1292, 2SK1307, 2SK1348..49, 2SK1906..
2SK1818(-MR)	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 20A, 50W, <0,25Ω(10A)	17c	Fujitsu	-
2SK1819(-MR)	MOS-N-FET-e	V-MOS, 450V, 5A, 35W, <1,5Ω(2,5A)	17c	Fjd	2SK1231..32, 2SK1608, 2SK2114..15..
2SK182	MOS-N-FET-e	V-MOS, Pow, 600V, 60A, 1000W, 250/300nS	-	old	-

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2SK1820(-01)L,S	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 6A, 80W, <1,6Ω(5A)	30c$	Fjd	2SK1314, 2SK1703S, 2SK2365Z
2SK1821(-01M)	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 2A, 30W, <6,5Ω(5A)	17c	Fujitsu	BUK445-600, 2SK1142, 2SK1758, 2SK1953
2SK1822(-01M,MR)	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 35W, <0,11Ω(10A)	17c	Fjd	2SK943, 2SK1214, 2SK1290, 2SK1345..
2SK1823(-01R)	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 80W, <17mΩ(20A)	18c	Fjd	2SK1298, 2SK1653, 2SK1666, 2SK2203
2SK1824	MOS-N-FET-e*	V-MOS, LogL, 30V, ±0,1A, <8Ω(10mA)	35a(1,6mm)	Nec	2SK3019
2SK1825	MOS-N-FET-e*	V-MOS+Di(S→G), 50V, 0,05A, <50Ω(10mA)	41c	Tos	-
2SK1826	MOS-N-FET-e*	-	35	Tos	→2SK1826
2SK1827	MOS-N-FET-e*	-	35(2mm)	Tos	→2SK1827
2SK1828	MOS-N-FET-e*	V-MOS+Di(S→G), 20V, 0,05A, <40Ω(10mA)	35a	Tos	-
2SK1829	MOS-N-FET-e*	-	35(2mm)	Tos	→2SK1829
2SK183	MOS-N-FET-e	=2SK182: 800V	-	old	-
2SK1830	MOS-N-FET-e*	-	35(1,6mm)	Tos	→2SK1830
2SK1831	MOS-N-FET-e*	=2SK1161: Iso, 50W	?18c	Hit	2SK1225, 2SK1206, 2SK1328..29, 2SK1696..
2SK1832	MOS-N-FET-e*	=2SK1162: Iso, 50W	?18c	Hit	2SK1206, 2SK1329, 2SK1523, 2SK1696
2SK1833	MOS-N-FET-e	V-MOS, 500V, ±2,5A, 40W, <4Ω(1,5A)	17c	Mat	BUK445-500, 2SK1767, 2SK1863, 2SK1989
2SK1834	MOS-N-FET-e	V-MOS, 800V, ±2A, 40W, <7Ω(5A), 35/85nS	17c	Mat	BUK446-800, 2SK1142, 2SK1459, 2SK1611..
2SK1835	MOS-N-FET-e	V-MOS, 1500V, 4A, 125W, <7Ω(5A)	18c$	Hit	-
2SK1836	MOS-N-FET-e*	V-MOS, 450V, 50A, 250W, <0,1©(20A)	77c$	Hit	2SK1521..22
2SK1837	MOS-N-FET-e*	=2SK1836: 500V, <0,11Ω(20A)	77c$	Hit	2SK1522
2SK1838(L,S)	MOS-N-FET-e*	V-MOS, 250V, 1A, 10W, <8Ω(0,5A)	30c$	Hit	2SK945, 2SK1195
2SK1839	MOS-N-FET-e	=2SK1841: SMD	35d(2mm)	Sanyo	-
2SK184	N-FET	GenP, 50V, Idss>0,6mA, Up<1,5V	41a	Tos	2SK68, 2SK106
2SK1840	MOS-N-FET-e	=2SK1841: SMD	35f	Sanyo	2SK1590
2SK1841	MOS-N-FET-e	V-MOS, LogL, 30V, 0,1A, 0,2W, <25Ω(10mA)	40f	Sanyo	2SK1398
2SK1842	N-FET	IR-Sensor, 40V, Idss>30µA, Up<3V	35f	Mat	-
2SK1842-P:	N-FET	-	35	Sam	→2SK1842
2SK1842-Q:	N-FET	-	35	Sam	→2SK1842
2SK1842-R:	N-FET	-	35	Sam	→2SK1842
2SK1842-S:	N-FET	-	35	Sam	→2SK1842
2SK1846	MOS-N-FET-e	V-MOS, 800V, ±3A, 40W, <4Ω(5A), 40/140nS	30c$	Mat	2SK1528, 2SK1858, 2SK2005, 2SK2029..
2SK1847	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,5A, <1,1Ω	35a	Sanyo	2SK3287
2SK1848	MOS-N-FET-e*	V-MOS, LogL, 60V, 0,4A, <1,6Ω	35a	Sanyo	2SK2911
2SK1849	MOS-N-FET-e	V-MOS, LogL, 100V, 0,25A, <4,2Ω(0,1(A)	35a	Sanyo	2SK2911
2SK185	N-FET	Dual, 30V, Idss>0,9mA, Up<1,49V	7e+7a	Son	-
2SK1850	MOS-N-FET-e*	V-MOS, LogL, 60V, ±10A, <0,07Ω(5A)	78c	Nec	-
2SK1851	MOS-N-FET-e*	V-MOS, LogL, 60V, ±15A, <45mΩ(5A)	78c	Nec	-
2SK1852	MOS-N-FET-e*	V-MOS, LogL, 100V, ±10A, <0,15Ω(5A)	78c	Nec	-
2SK1853	MOS-N-FET-e*	V-MOS, LogL, 100V, ±15A, <0,08Ω(5A)	78c	Nec	-
2SK1854	MOS-N-FET-e	V-MOS, DC-DC, 400V, 6A, 40W, <1Ω(2,5A)	17c	Tos	2SK1231, 2SK1351, 2SK1608, 2SK1627,..
2SK1855	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,7Ω(5A)	18c$	Tos	2SK896, 2SK1488, 2SK1753, 2SK1785,..
2SK1856	MOS-N-FET-e	V-MOS, 500V, 15A, 150W, <0,5e	18c$	Tos	2SK899, 2SK1610, 2SK1745, 2SK1757,..
2SK1858	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 60W, <5Ω(1,5A)	30c$	Tos	2SK1510, 2SK1528, 2SK1659, 2SK1846..
2SK1859	MOS-N-FET-e*	=2SK1341: Iso, 60W	?18c	Hit	2SK1464, 2SK1684..85, 2SK1775
2SK186	N-FET	GenP, LN, 40V, Idss>1,6mA, Up<1,5V	7a	Hit	2SK187, 2SK364, 2SK366
2SK1860	N-FET	Cond.-microphone amp, 20V, 2mA, Idss<0,4mA	35	Mat	-
2SK1861	MOS-N-FET-e*	V-MOS, LogL, 150V, 4A, 10W, <0,6Ω(5A)	30c$	Shi	2SK1560
2SK1862	MOS-N-FET-e*	=2SK1153: Iso, 25W	17c	Hit	BUK445-450..-500, 2SK1572, 2SK1767,..
2SK1863	MOS-N-FET-e*	=2SK1154: Iso, 25W	17c	Hit	BUK445-500, 2SK1572, 2SK1767,..
2SK1864	MOS-N-FET-e	V-MOS, 500V, 8A, 100W, <0,85Ω(5A)	30c$	Tos	2SK1316, 2SK2187, 2SK2360-Z
2SK1865	MOS-N-FET-e	V-MOS, 500V, 12A, 100W, <0,07Ω(5A)	30c$	Tos	2SK2366Z
2SK1867	MOS-N-FET-e	V-MOS, 900V, ±2A, 15W, <4,85Ω(5A)	78c	Mat	(2SK1143, 2SK1275, 2SK1459)
2SK1868	MOS-N-FET-e	V-MOS, LogL, 60V, ±3A, 15W, <0,2Ω(5A)	78c	Mat	(BUK541-60, 2SK1255)
2SK1869(L,S)(A)	MOS-N-FET-e*	=2SK1400: 50W	30c$	Hit	-
2SK187	N-FET	GenP, LN, 40V, Idss>2,5mA, Up<1,5V	7a	Hit	2SK186, 2SK364, 2SK366
2SK1871	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 40W, <80mΩ(10A)	30c$	Sanyo	2SK1648, 2SK1898, 2SK2322
2SK1872	MOS-N-FET-e	V-MOS, 50V, 25A, 40W, <40mΩ(10A)	17c	Toshiba	2SK943, 2SK1290, 2SK1420, 2SK1346..
2SK1875	MOS-N-FET-e	=2SK709: SMD	35f(2mm)	Tos	-
2SK1876	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,65e	17c$	Fjd	2SK1442, 2SK2365..66
2SK1877	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 12W, <75mΩ(5A)	14b	Hit	-
2SK1878	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 12W, <0,14Ω(5A)	14b	Hit	-
2SK1879	MOS-N-FET-e*	V-MOS, 60V, 45A, 125W, <0,03Ω(20A)	18c$	Tos	BUK439-60, 2SK849, 2SK857, 2SK1379..
2SK1880(L,S)	MOS-N-FET-e*	V-MOS, 600V, 1,5A, 20W, <8Ω(5A)	30c$	Hit	(2SK1327)
2SK1881(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 20A, 45W, <0,11Ω(10A)	30c$	Fjd	2SK1918, 2SK1967, 2SK2286, 2SK2311
2SK1882	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 40W, <0,05Ω(10A)	17c	Tos	2SK943, 2SK1095, 2SK1214, 2SK1345

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2SK1883	MOS-N-FET-e	V-MOS, LogL, 30V, 18A, 50W, <0,055Ω(5A)	17c$	Sanyo	2SK942, 2SK972, 2SK1115, 2SK1910
2SK1884	MOS-N-FET-e	V-MOS, LogL, 30V, 22A, 60W, <0,04Ω(10A)	17c$	Sanyo	2SK942, 2SK972, 2SK1115, 2SK1910
2SK1885	MOS-N-FET-e	V-MOS, LogL, 30V, 35A, 70W, <25mΩ(10A)	17c$	Sanyo	2SK1291, 2SK1296
2SK1886	MOS-N-FET-e*	V-MOS, LogL, 30V, 15A, 25W, <55mΩ(5A)	17c	Sanyo	2SK1094, 2SK1286
2SK1887	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 25W, <40mΩ(10A)	17c	Sanyo	2SK943, 2SK1290, 2SK1345, 2SK1348..49
2SK1888	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 30W, <25mΩ(10A)	17c	Sanyo	2SK943, 2SK1290, 2SK1345, 2SK1348..49
2SK1889	MOS-N-FET-e*	V-MOS, LogL, 30V, 18A, 50W, <55mΩ(5A)	30c$	Sanyo	2SK1648, 2SK1898
2SK1890	MOS-N-FET-e*	V-MOS, LogL, 30V, 22A, 60W, <40mΩ(10A)	30c$	Sanyo	2SK1622
2SK1891	MOS-N-FET-e*	V-MOS, LogL, 30V, 35A, 70W, <25mΩ(10A)	30c$	Sanyo	2SK1900
2SK1892	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 50W, <80mΩ(5A)	17c$	Sanyo	BUK552-60, 2SK942, 2SK1115..16, 2SK1347
2SK1893	MOS-N-FET-e	V-MOS, LogL, 60V, 18A, 60W, <70mΩ(5A)	17c$	Sanyo	BUK552-60, 2SK942, 2SK1115..16, 2SK1347
2SK1894	MOS-N-FET-e	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(10A)	17c$	Sanyo	2SK1291, 2SK1296
2SK1895	MOS-N-FET-e*	V-MOS, LogL, 60V, 12A, 25W, <80mΩ(5A)	17c	Sanyo	2SK1093, 2SK1256, 2SK1305..06, 2SK1344..
2SK1896	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 25W, <70mΩ(5A)	17c	Sanyo	2SK943, 2SK1214, 2SK1345
2SK1897	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 30W, <0,04Ω(10A)	17c	Sanyo	2SK943, 2SK1095, 2SK1214, 2SK1345
2SK1898	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <80mΩ(5A)	30c$	Sanyo	2SK1648
2SK1899	MOS-N-FET-e*	V-MOS, LogL, 60V, 18A, 60W, <70mΩ(5A)	30c$	Sanyo	2SK1622
2SK19(TM)	N-FET	FM/VHF, 18V, Idss=3..24mA, Up=3V	7d	Tos, Mic	BFS71, BFS80, BFW11, 2N3822, 2N4416..
2SK190	N-FET	AF, LN, 40V, 0,2A, Idss>6mA, Up<1,5V	7a(9mm)	Hit	-
2SK1900	MOS-N-FET-e*	V-MOS, LogL, 60V, 30A, 70W, <40mΩ(10A)	30c$	Sanyo	-
2SK1901	MOS-N-FET-e	V-MOS, LogL, 100V, 12A, 50W, <0,16Ω(5A)	17c$	Sanyo	2SK1300..01, 2SK1559, 2SK1561
2SK1902	MOS-N-FET-e	V-MOS, LogL, 100V, 15A, 60W, <135mΩ(5A)	17c$	Sanyo	2SK1301, 2SK1559, 2SK1561
2SK1903	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 70W, <80mΩ(10A)	17c$	Sanyo	2SK1116, 2SK1302, 2SK1347
2SK1904	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 25W, <0,16Ω(5A)	17c	Sanyo	BUK545-100, 2SK1305, 2SK1035
2SK1905	MOS-N-FET-e*	V-MOS, LogL, 100V, 12A, 25W, <135mΩ(5A)	17c	Sanyo	2SK1034, 2SK1288, 2SK1306
2SK1906	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 30W, <0,08Ω(10A)	17c	Sanyo	2SK1292, 2SK1307, 2SK1348..49
2SK1907	MOS-N-FET-e*	V-MOS, LogL, 100V, 12A, 50W, <0,16Ω(5A)	30c$	Sanyo	2SK1623
2SK1908	MOS-N-FET-e*	V-MOS, LogL, 100V, 15A, 60W, <135mΩ(5A)	30c$	Sanyo	2SK1623
2SK1909	MOS-N-FET-e*	V-MOS, LogL, 100V, 25A, 70W, <80mΩ(10A)	30c$	Sanyo	-
2SK191	N-FET	AF, 15V, 0,5A, Idss>10mA, Up<3V	7a(9mm)	Hit	-
2SK1910	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <0,04Ω(10A)	17c$	Hit	2SK942, 2SK972, 2SK1115
2SK1911	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 75W, <22mΩ(20A)	17c$	Hit	BUK556-60, 2SK1542
2SK1913	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <1,8Ω(2,5A)	17c	Tos	2SK1118, 2SK1637, 2SK2045, 2SK2097
2SK1914	MOS-N-FET-e	V-MOS, 800V, 1,5A, 15W, <6,5Ω(0,7(A)	?30c$	Tos	-
2SK1915	MOS-N-FET-e	V-MOS, 600V, 6A, 100W, <1,25Ω(5A)	30c$	Tos	2SK1624, 2SK2089
2SK1916(-01R)	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 18A, 80W, <0,45Ω(5A)	18c	Fjd	2SK1406, 2SK1453, 2SK1525
2SK1917-M(-MR)	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,4Ω(5A)	17c	Fjd	2SK526, 2SK1036, 2SK2011, 2SK2436
2SK1918(L,S)	MOS-N-FET-e*	=2SK1910:	30c$	Hit	2SK1622, 2SK2311
2SK1919(L,S)	MOS-N-FET-e*	=2SK1911:	30c$	Hit	2SK1792, 2SK2164, 2SK2266
2SK192(A)	N-FET	FM/VHF, 18V, Idss>3mA, Up<3V	41d	Tos	BF410B..C
2SK1920	MOS-N-FET-e*	V-MOS, Sw, Pow, 250V, 4A, 30W, <0,7Ω(5A)	30c$	Sanyo	2SK2099, 2SK3342
2SK1921	MOS-N-FET-e*	V-MOS, Sw, Pow, 250V, 4A, 50W, <0,7Ω(5A)	17c$	Sanyo	2SK477, 2SK741, 2SK924, 2SK1391
2SK1922	MOS-N-FET-e	V-MOS, 600V, 2A, 50W, <4,3Ω(5A)	17c$	Sanyo	BUZ80, 2SK858, 2SK1323..24
2SK1923	MOS-N-FET-e	V-MOS, Sw-Reg, 600V, 4A, 60W, <1,8Ω(5A)	17c$	Sanyo	2SK1402, 2SK1501, 2SK1639, 2SK1643
2SK1924	MOS-N-FET-e	V-MOS, Sw-Reg, 600V, 6A, 70W, <1,5Ω(5A)	17c$	Sanyo	2SK1117, 2SK1643
2SK1925	MOS-N-FET-e	V-MOS, Sw-Reg, 600V, 8A, 120W, <1,2Ω(5A)	18c$	Sanyo	BUZ332A, 2SK1032
2SK1926	MOS-N-FET-e	V-MOS, 60V, 15A, 50W, <0,1Ω	17c	Toshiba	2SK943, 2SK1214, 2SK1345
2SK1927	MOS-N-FET-e	V-MOS, 100V, 15A, 60W, <0,18Ω(5A)	30c$	Tos	2SK1623, 2SK1909
2SK1928	MOS-N-FET-e	V-MOS, 100V, 27A, 80W, <85mΩ(10A)	30c$	Tos	2SK1813
2SK1929	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω(5A)	30c$	Tos	2SK1528, 2SK2006
2SK193	N-FET	FM, 20V, Idss>0,5mA, Up<2,5V	40f	Nec	BF410A, 2SK195, 2SK212
2SK1930	MOS-N-FET-e	V-MOS, 1000V, 4A, 80W, <3,8Ω(5A)	30c$	Tos	2SK2004
2SK1931	MOS-N-FET-e	V-MOS, 200V, 5A, 20W, <0,65Ω(2,5A)	30c$	Shi	2SK1920, 2SK2099
2SK1933	MOS-N-FET-e*	V-MOS, 900V, 10A, 150W, <1,2Ω(5A)	18c$	Hit	2SK1796
2SK1934	MOS-N-FET-e*	V-MOS, 1000V, 8A, 150W, <1,6Ω(5A)	18c$	Hit	2SK1120
2SK1936-01	MOS-N-FET-e	V-MOS, 500V, 10A, 100W, <0,76Ω(5A)	18c$	Fjd	2SK644, 2SK724, 2SK1488, 2SK1785..
2SK1937-01	MOS-N-FET-e	V-MOS, 500V, 15A, 125W, <0,48Ω(7,2A)	18c$	Fjd	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK1938-01(-01R)	MOS-N-FET-e	V-MOS, 500V, 18A, 100W, <0,35Ω(5A)	18c	Fjd	2SK1406, 2SK1525
2SK1939-01	MOS-N-FET-e	V-MOS, 600V, 8A, 100W, <1,2Ω(5A)	18c$	Fjd	BUZ332A, 2SK1032, 2SK1925, 2SK2834
2SK194	N-FET	Dual, 40V, 50mA, Idss>5mA, Up<1,2V	7e+7a	Nec	-
2SK1940-01	MOS-N-FET-e	V-MOS, 600V, 12A, 125W, <0,75Ω(5A)	18c$	Fjd	BUZ334, 2SK1723, 2SK1968, 2SK2699
2SK1941-01	MOS-N-FET-e	V-MOS, 600V, 16A, 100W, <0,55Ω(5A)	18c	Fjd	2SK1405
2SK1942-01	MOS-N-FET-e	V-MOS, 900V, 3A, 80W, <4Ω(1,5A)	18c$	Fjd	2SK696, 2SK726..727, 2SK794, 2SK1341,..
2SK1943-01	MOS-N-FET-e	V-MOS, 900V, 5A, 80W, <2,8Ω(2,5A)	17c$	Fjd	2SK1457, 2SK1501, 2SK1639, 2SK1643

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2SK1944-01	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω(2,5A)	18c$	Fjd	2SK727, 2SK794, 2SK1341, 2SK1760,..
2SK1945-01L,S	MOS-N-FET-e	V-MOS, 900V, 5A, 80W, <2,8Ω(2,5A)	30c$	Fjd	2SK1528, 2SK2004, 2SK2006, 2SK2670
2SK1946-01M(MR)	MOS-N-FET-e	V-MOS, 60V, 45A, 50W, <22mΩ(22,5A)	17c	Fujitsu	2SK1257, 2SK1653, 2SK1952, 2SK2120
2SK1947	MOS-N-FET-e*	FREDFET, 250V, 50A, 200W, <60mΩ(20A)	77c$	Hit	-
2SK1948	MOS-N-FET-e*	V-MOS, 250V, 50A, 200W, <60mΩ(20A)	77c$	Hit	-
2SK1949(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,15Ω(5A)	30c$	Hit	2SK1112, 2SK1471, 2SK1719
2SK195	N-FET	FM, 20V, Idss>0,5mA, Up<2,5V	7f	Nec	BF410A, 2SK193, 2SK212, 2SK606
2SK1950(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 3A, 10W, <0,23Ω(5A)	30c$	Hit	2SK974, 2SK1282, 2SK1254, 2SK1299,..
2SK1951	MOS-N-FET-e*	=2SK1910: Iso, 35W	17c	Hit	2SK943, 2SK1095, 2SK1345..46, 2SK1307,..
2SK1952	MOS-N-FET-e*	=2SK1911: Iso, 35W	17c	Hit	2SK1257, 2SK1653
2SK1953	MOS-N-FET-e*	V-MOS, Sw, Pow, 600V, ±2A, 25W, <5Ω(5A)	17c	Nec	BUK445-600, 2SK1142, 2SK1834
2SK1954(-Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 180V, ±4A, 20W, <0,65Ω(5A)	30c$	Nec	2SK1920, 2SK2099
2SK1957	MOS-N-FET-e*	V-MOS, 200V, 7A, 30W, <0,45Ω(5A)	17c	Hit	BUK545-200, 2SK1568..69, 2SK1668
2SK1958	MOS-N-FET-e*	V-MOS, LogL, 16V, ±0,1A, <12Ω(10m)	35a(2mm)	Nec	-
2SK1959	MOS-N-FET-e*	V-MOS, LogL, 16V, ±2A, <0,5Ω(5A)	39b	Nec	2SK1311, 2SK1470, 2SK1717
2SK196	MOS-N-FET-e	V-MOS, 160V, 0,5A, 0,8W, <15Ω, 20/30nS	2e*	Hit	BSS93
2SK1960	MOS-N-FET-e*	V-MOS, LogL, 16V, ±3A, <0,2Ω(1,5A	39b	Nec	2SK2054
2SK1961	N-FET	VHF/UHF, 15V, Idss=40..75mA, Up<4,5V	7e	Sanyo	-
2SK1962	GaAs-N-FET	UHF, 4V, 60mA, Idss>12mA, 12GHz	51y	Mat	-
2SK1963	GaAs-N-FET	UHF, 4V, 60mA, Idss>12mA, 12GHz	51y	Mat	-
2SK1964	GaAs-N-FET	UHF, 4V, 60mA, Idss>12mA, 12GHz	51y	Mat	-
2SK1967	MOS-N-FET-e	V-MOS, LogL, 60V, ±20A, 45W, <70mΩ(10A)	30c$	Mat	2SK1622, 2SK1918, 2SK2311
2SK1968	MOS-N-FET-e*	V-MOS, 600V, 12A, 100W, <0,88Ω(5A)	18c$	Hit	BUZ334, 2SK1723
2SK1969-01	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 125W, <17mΩ(20A)	18c$	Fjd	BUK539-60, 2SK1258, 2SK1379..80
2SK197	N-FET	VHF, 18V, Idss>2mA, Up<4V	35c	Hit	2SK210, 2SK217
2SK1971	MOS-N-FET-e*	V-MOS, 500V, 35A, 200W, <0,23Ω(10A)	77c$	Hit	2SK1520, 2SK1629
2SK1973(F5)	MOS-N-FET-e	V-MOS, 60V, 2A, 20W, <0,35Ω(5A)	30c$	Rhm	2SK462, 2SK973, 2SK1763
2SK1974	MOS-N-FET-e	V-MOS, 60V, 10A, 30W, <0,35Ω(5A)	17c	Rhm	BUK442-60, 2SK1093, 2SK1256, 2SK1344
2SK1975	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,35Ω(5A)	16c($)	Rhm	2SK724, 2SK899, 2SK1488, 2SK1757..
2SK1976	MOS-N-FET-e	V-MOS, 450V, 5A, 30W, <1,4Ω(5A)	17c	Rhm	2SK1231..32, 2SK1608, 2SK1626..27,..
2SK197-E	N-FET	-	35	Hit	→2SK197
2SK198	N-FET	AF, LN, 30V, ±20mA, Idss>0,5mA	35f	Mat	-
2SK1980	MOS-N-FET-e	V-MOS, 800V, ±2A, 40W, <7Ω(5A), 35/85nS	30c$	Mat	2SK1647, 2SK1846, 2SK1858
2SK1981-01	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 80W, <0,76Ω(5A)	17c$	Fjd	2SK1503, 2SK2366
2SK1982-01M(MR)	MOS-N-FET-e	=2SK1981: Iso, 50W	17c	Fjd	-
2SK1983-01	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 60W, <4Ω(1,5A)	17c$	Fjd	BUK456-1000, 2SK1601, 2SK1638, 2SK2479..
2SK1984-01M(MR)	MOS-N-FET-e	=2SK1983: Iso	17c	Fjd	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK1985-01M(MR)	MOS-N-FET-e	V-MOS, 900V, 5A, 50W, <2,8Ω(2,5A)	17c	Fjd	2SK1808
2SK1986-01	MOS-N-FET-e	V-MOS, 1000V, 4A, 80W, <3,6Ω(5A)	17c$	Fjd	2SK1119
2SK1987	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, ±7A, 30W, <0,5Ω(5A)	17c	NEC	2SK1478, 2SK1568..69, 2SK1668
2SK1988	MOS-N-FET-e*	V-MOS, 450V, ±2,5A, 30W, <2,8Ω(1,5A)	17c	Nec	BUK444-450, 2SK1833
2SK1989	MOS-N-FET-e*	=2SK1988: 500V, <3Ω(1,5A)	17c	Nec	BUK444-500, 2SK1833
2SK198-P	N-FET	-	35	Mat	→2SK198
2SK198-Q	N-FET	-	35	Mat	→2SK198
2SK198-R	N-FET	-	35	Mat	→2SK198
2SK199	N-FET	HF, 15V, Idss<12mA	35c	Mat	-
2SK1990	MOS-N-FET-e*	V-MOS, 450V, ±4,5A, 30W, <1,4Ω(2,5A)	17c	Nec	2SK1351, 2SK1445, 2SK1608, 2SK1626..27..
2SK1991	MOS-N-FET-e*	=2SK1990: 500V, <1,5Ω(2,5A)	17c	Nec	2SK1351, 2SK1232, 2SK1608, 2SK1627,..
2SK1992	MOS-N-FET-e*	V-MOS, 450V, ±6A, 35W, <0,9e(5A)	17c	Nec	2SK1352, 2SK1566..67, 2SK1609, 2SK1805..
2SK1993	MOS-N-FET-e*	=2SK1992: 500V, <1Ω(5A)	17c	Nec	2SK1352, 2SK1567, 2SK1609, 2SK1805,..
2SK1994	MOS-N-FET-e*	V-MOS, 900V, ±2A, 30W, <7,5Ω(5A)	17c	Nec	2SK1143, 2SK1174, 2SK1275
2SK1995	MOS-N-FET-e*	V-MOS, 900V, ±3A, 35W, <4Ω(5A)	17c	Nec	2SK1356, 2SK1460
2SK1996	GaAs-N-FET-d	SHF, 3V, 60mA, Idss=15..60mA, 12GHz	51y	Tos	-
2SK1997	MOS-N-FET-e*	V-MOS, LogL, 60V, 36A, 40W, <0,03Ω(10A)	17c	Tos	2SK1257, 2SK1653, 2SK1952, 2SK2120
2SK1998	MOS-N-FET-e	V-MOS, LogL, 60V, 45A, 125W, <0,03Ω(20A)	18c$	Tos	BUK539-60, 2SK1379, 2SK1297, 2SK1514,..
2SK1999	MOS-N-FET-e*	V-MOS, Dual, 120V, 12A, Pq>150W(200MHz)	-	Hit	-
2SK2000-R	MOS-N-FET-e	V-MOS, 100V, 32A, 80W, <0,06Ω	18c	Fjd	2SK1149, 2SK1435..36
2SK2002-01M(MR)	MOS-N-FET-e	V-MOS, 600V, 3A, 30W, <4,5Ω(1,5A)	17c	Fjd	BUZ90AF, 2SK1572, 2SK2144, 2SK2325..
2SK2003-01M(MR)	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <2,4Ω(5A)	17c	Fjd	2SK1118, 2SK2044, 2SK2097, 2SK2118..
2SK2004-01L,S	MOS-N-FET-e	V-MOS, 1000V, 4A, 80W, <3,6Ω(5A)	30c$	Fjd	MTB3N100E
2SK2005	MOS-N-FET-e	V-MOS, 900V, 3A, 50W, <5Ω(1,5A)	30c$	Shi	2SK1510, 2SK1659, 2SK2029
2SK2006	MOS-N-FET-e	V-MOS, 900V, 5A, 65W, <3Ω(2,5A)	30c$	Shi	2SK1501-Z, 2SK1528
2SK2007	MOS-N-FET-e*	V-MOS, 250V, 20A, 100W, <0,15Ω(10A)	18c$	Hit	2SK901, 2SK944, 2SK1641, 2SK2058
2SK2008	MOS-N-FET-e*	=2SK2007: Iso, 60W	?18c	Hit	2SK1406, 2SK1525, 2SK1670

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2SK2009	MOS-N-FET-e*	V-MOS, 30V, 0,2A, <2Ω(50mA)	35a	Tos	-
2SK201	GaAs-N-FET	UHF, C..X-Band, 10V, 400mA, 8GHz	52y	Nec	-
2SK2010	MOS-N-FET-e*	V-MOS, 250V, 4A, 25W, <0,7Ω(5A)	17c	Sanyo	2SK1478, 2SK1568..69, 2SK1668, 2SK1987
2SK2011	MOS-N-FET-e*	V-MOS, 250V, 12A, 30W, <0,35Ω(5A)	17c	Sanyo	2SK1036, 2SK1762
2SK2012	MOS-N-FET-e*	V-MOS, 250V, 18A, 40W, <0,16Ω(10A)	17c	Sanyo	2SK2255
2SK2013	MOS-N-FET-e	V-MOS, 180V, 1A, 25W	17c	Tos	2SK528..529, 2SK1443
2SK2014	MOS-N-FET-e	V-MOS, LogL, 100V, ±1A 10W, <1Ω(0,5A)	30c$	Mat	-
2SK2015	MOS-N-FET-e	V-MOS, LogL, 150V, ±3A, 10W, <1,1Ω(5A)	30c$	Mat	2SK1335
2SK2016	MOS-N-FET-e	V-MOS, LogL, 100V, ±5A, 10W, <0,47Ω(5A)	30c$	Mat	2SK1474, 2SK1804, 2SK2399
2SK2017	MOS-N-FET-e	V-MOS, 550V, 1A, 10W, <8Ω(0,5A)	30c$	Mat	2SK1327, 2SK1880
2SK2018-01(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 20W, <0,16Ω(5A)	30c$	Fjd	MTD12N06EZL, 2SK2414, 2SK3023
2SK2019-01	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 3,5A, 40W, <3Ω(1,5A)	17c$	Fjd	2SK1154, 2SK1244, 2SK1494
2SK2020-01M(MR)	MOS-N-FET-e	=2SK2019: Iso, 30W	17c	Fjd	BUK445-500, 2SK1572, 2SK1767, 2SK2144..
2SK2021-01	MOS-N-FET-e	V-MOS, 500V, 5A, 60W, <1,6Ω(2,5A)	17c$	Fjd	BUZ41A..42, 2SK553, 2SK893, 2SK1246..
2SK2022-01M(MR)	MOS-N-FET-e	=2SK2021: Iso, 40W	17c	Fjd	2SK1351, 2SK1608, 2SK1627, 2SK2115..
2SK2023-01	MOS-N-FET-e	V-MOS, 600V, 3A, 40W, <4,5Ω(1,5A)	17c$	Fjd	BUK456-800, 2SK1600, 2SK2603
2SK2024-01	MOS-N-FET-e	=2SK2023:	18c$	Fjd	BUZ307, BUZ360..361, 2SK603
2SK2025-01	MOS-N-FET-e	V-MOS, 600V, 4A, 60W, <2,4Ω(5A)	17c$	Fjd	BUZ90, 2SK1117, 2SK1402, 2SK1809..
2SK2026-01	MOS-N-FET-e	=2SK2025:	18c$	Fjd	2SK695, 2SK793, 2SK1213, 2SK1403
2SK2027-01	MOS-N-FET-e	V-MOS, 600V, 8A, 80W, <1,2Ω(5A)	17c$	Fjd	BUK657-600, BUZ91, BUZ305, 2SK2140
2SK2028-01M(MR)	MOS-N-FET-e	=2SK2027: Iso, 50W	17c	Fjd	2SK2843, 2SK2996
2SK2029-01(L,S)	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 60W, <4Ω(1,5A)	30c$	Fjd	2SK1510, 2SK1528, 2SK1659, 2SK2005
2SK203	GaAs-N-FET	UHF, C..X-Band, 10V, 180mA, 8GHz	52y.e	Nec	-
2SK2030	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 5A, 20W, <0,14Ω(2,5A)	30c$	Tos	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK2032	MOS-N-FET-e	V-MOS, 450V, n13A, 100W, <0,45Ω(5A)	16c($)	Mat	2SK899, 2SK1678, 2SK1745, 2SK1757..
2SK2033	MOS-N-FET-e	V-MOS, +Di(S→G), 20V, 0,1A, <12Ω(10mA)	35a	Tos	-
2SK2034	MOS-N-FET-e*	-	35(2mm)	Tos	→2SK2034
2SK2035	MOS-N-FET-e*	-	35(1,6mm)	Tos	→2SK2035
2SK2036	MOS-N-FET-e	V-MOS, +Di(S→G), 20V, 0,1A, <6Ω(10mA)	35a	Tos	-
2SK2037	MOS-N-FET-e*	-	35(2mm)	Tos	→2SK2037
2SK2038	MOS-N-FET-e	V-MOS, 800V, 5A, 125W, <2,2Ω(5A)	18c$	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK2039	MOS-N-FET-e	V-MOS, 900V, 5A, 150W, <2,5Ω(5A)	18c$	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK2040(-Z)	MOS-N-FET-e*	V-MOS, 600V, ±2A, 20W, <5Ω(5A)	30c$	Nec	IRFRC20
2SK2041	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 60W, <95mΩ(5A)	30c$	Rhm	2SK1907, 2SK2282
2SK2042	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 5A, 60W, <1,4Ω(2,5A)	30c$	Rhm	2SK1313, 2SK1691, 2SK1750Z
2SK2043(LS)	MOS-N-FET-e	V-MOS, 600V, 2A, 25W, <4,3Ω(5A)	17c	Sanyo	BUK445-600, 2SK1142, 2SK1834
2SK2044(LS)	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,4Ω(5A)	17c	Sanyo	2SK1118, 2SK1404, 2SK1637
2SK2045(LS)	MOS-N-FET-e	V-MOS, 600V, 5,5A, 35W, <1,5Ω(5A)	17c	Sanyo	2SK1118, 2SK1404, 2SK2101
2SK2046	MOS-N-FET-e*	V-MOS, LogL, 30V, 12A, 30W, <0,07Ω(5A)	30c$	Sanyo	2SK1754, 2SK2018, 2SK2329, 2SK2414
2SK2047	MOS-N-FET-e	V-MOS, 550V, n1,2A, 15W, <8Ω(0,5A)	?30c$	Mat	(2SK1746)
2SK2048(-01)L,S	MOS-N-FET-e	V-MOS, 30V, 35A, 60W, <22mΩ(17,5A)	30c$	Fjd	2SK1919, 2SK2164, 2SK2266, 2SK2376..
2SK2049	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 80W, <25mΩ(20A)	17c$	Fjd	BUK556-60, MTP52N06VL, 2SK1542, 2SK2499
2SK2050	MOS-N-FET-e	V-MOS, LogL, 100V, 30A, 80W, <55mΩ(10A)	17c$	Fjd	2SK1293, 2SK2314
2SK2051(-01)L,S	MOS-N-FET-e	V-MOS, 250V, 10A, 80W, <0,4Ω(5A)	30c$	Fjd	2SK1636, 2SK2133-Z, 2SK2254
2SK2052(-R)	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <1,1Ω(5A)	18c	Fjd	2SK1206, 2SK1329, 2SK1523, 2SK1696..
2SK2053	MOS-N-FET-e*	V-MOS, LogL, 16V, ±5A, <0,12Ω(2,5A)	39b	Nec	-
2SK2054	MOS-N-FET-e*	V-MOS, LogL, 60V, ±3A, <0,2Ω(1,5A)	39b	Nec	-
2SK2055	MOS-N-FET-e*	V-MOS, LogL, 100V, ±2A, <0,35Ω(5A)	39b	Nec	2SK1473
2SK2056	MOS-N-FET-e	V-MOS, 800V, 4A, 40W, <2,4Ω(5A)	17c	Tos	2SK1808, 2SK1985, 2SK2044, 2SK2118..
2SK2057	MOS-N-FET-e	V-MOS, 500V, 20A, 150W, <0,31Ω(10A)	18c$	Tos	2SK1170, 2SK1411, 2SK1500, 2SK1680..
2SK2058	MOS-N-FET-e*	V-MOS, Sw, Pow, 250V, 25A, 120W, <0,16Ω(10A)	18c$	Sanyo	2SK901, 2SK944, 2SK1641, 2SK1673..74
2SK2059(L,S)	MOS-N-FET-e*	V-MOS, 600V, 3A, 20W, <5Ω(5A)	30c$	Hit	-
2SK2060	MOS-N-FET-e	V-MOS, 600V, 8A, <0,25e	30c$	Shi	2SK2889, 2SK2908
2SK2061	MOS-N-FET-e*	V-MOS, 600V, 16A, 150W, <0,45e	16c$	Shi	2SK1573
2SK2062	MOS-N-FET-e	V-MOS, 250V, 10A, 50W, <0,5Ω(5A)	30c$	Shi	2SK1636, 2SK2133-Z, 2SK2254, 2SK2598
2SK2063	MOS-N-FET-e	V-MOS, 250V, 20A, 65W, <0,25Ω(10A)	30c$	Shi	2SK2254
2SK2064	MOS-N-FET-e	V-MOS, 300V, 10A, 50W, <0,7Ω(5A)	30c$	Shi	MTB10N40E
2SK2065	MOS-N-FET-e	V-MOS, 300V, 20A, 65W, <0,35Ω	30c$	Shi	-
2SK2066	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <2,3e, 45/75nS	30c$	Shi	2SK1314, 2SK1494Z, 2SK1721
2SK2067	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,1Ω, 50/90nS	30c$	Shi	2SK1314, 2SK1703S, 2SK1722, 2SK2356Z..
2SK2068	MOS-N-FET-e	V-MOS, 500V, 8A, 60W, <0,85e, 60/120nS	30c$	Shi	2SK1316, 2SK1541, 2SK2360-Z, 2SK2776..
2SK2069	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,7Ω, 70/143nS	30c$	Shi	2SK2187, 2SK2366Z
2SK2070	MOS-N-FET-e*	V-MOS, LogL, 100V, ±1,5A, <0,35Ω(5A)	9c	Nec	-
2SK2071-01(L,S)	MOS-N-FET-e	V-MOS, 600V, 2A, 20W, <6,5Ω(5A)	30c$	Fjd	IRFRC20, 2SK2040, 2SK2865

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2SK2072-01(L,S)	MOS-N-FET-e	V-MOS, 800V, 6A, 80W, <2,1Ω(5A)	30c$	Fjd	SSW6N80A
2SK2073	N-FET	=2SK2074:SMD	35f	Sanyo	-
2SK2074	N-FET	AM-Tuner, 15V, Idss>6mA, Up<1,2V	40e	Sanyo	-
2SK2075	MOS-N-FET-e*	V-MOS, 250V, 20A, 100W, <0,13Ω(10A)	18c$	Hit	2SK901, 2SK944, 2SK1641, 2SK2007,
2SK2076	N-FET	GenP, 30V, Idss>0,4mA, Up<1,5V	35e,f	Sanyo	-
2SK2076-14	N-FET	-	35	Sanyo	→2SK2076
2SK2076-15	N-FET	-	35	Sanyo	→2SK2076
2SK2077	MOS-N-FET-e	V-MOS, 800V, 7A, 150W, <1,7Ω(3,5A)	18c$	Tos	2SK1342, 2SK1358, 2SK1502, 2SK1795
2SK2078	MOS-N-FET-e	V-MOS, 800V, 9A, 150W, <1,2Ω(5A)	18c$	Tos	2SK1796, 2SK1933
2SK208	N-FET	AF-Pre, 50V, Idss>0,3mA, Up<5V	35f	Tos	-
2SK2080-01(R)	MOS-N-FET-e	V-MOS, 500V, 15A, 80W, <0,55Ω(5A)	18c	Fjd	2SK1269, 2SK1331, 2SK1405, 2SK1524
2SK2081-01	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,6Ω(5A)	18c$	Fjd	BUZ338, 2SK1610, 2SK1745, 2SK1785
2SK2082-01	MOS-N-FET-e	V-MOS, 900V, 9A, 150W, <1,4Ω(4,5A)	18c$	Fjd	2SK1796, 2SK1933, 2SK2488, 2SK2676
2SK2083	MOS-N-FET-e	V-MOS, 900V, 5A, 70W, <3,6Ω(5A)	30c$	Sanyo	2SK1501Z, 2SK1528, 2SK2006, 2SK2670
2SK2084(L,S)	MOS-N-FET-e*	V-MOS, LogL, 20V, 7A, 20W, <53mΩ(5A)	30c$	Hit	2SK1472, 2SK1748
2SK2085	MOS-N-FET-e*	V-MOS, LogL, 100V, 1A, 0,9W, <0,9Ω(0,5A)	7c(9mm)	Hit	2SK1736
2SK2088	MOS-N-FET-e	V-MOS, 200V, 10A, 60W, <0,4Ω(5A)	30c$	Tos	2SK1636, 2SK2133-Z, 2SK2254
2SK2089	MOS-N-FET-e	V-MOS, 800V, 5A, 100W, <2,4Ω(5A)	30c$	Tos	2SK1528
2SK208-G	N-FET	-	35	Tos	→2SK208
2SK208-O	N-FET	-	35	Tos	→2SK208
2SK208-R	N-FET	-	35	Tos	→2SK208
2SK208-Y	N-FET	-	35	Tos	→2SK208
2SK209	N-FET	GenP, 50V, Idss>0,6mA, Up<1,5V	35f	Tos	2SK94, 2SK425
2SK2090	MOS-N-FET-e*	V-MOS, LogL, 50V, ±0,1A, <20Ω(10mA)	35a(2mm)	Nec	-
2SK2091	N-FET	=2SK2076:	35a(2mm)	Sanyo	-
2SK2094	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, 20W, <0,35Ω(5A)	30c$	Rhm	2SK973, 2SK1763
2SK2095(N)	MOS-N-FET-e	V-MOS, LogL, 60V, 10A, 30W, <95mΩ(5A)	17c	Rohm	2SK1093, 2SK1256, 2SK1305..06, 2SK1344
2SK2096	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <22mΩ(20A)	18c$	Hit	2SK1297, 2SK1514, 2SK1665
2SK2097	MOS-N-FET-e*	V-MOS, 600V, 4A, 35W, <2,4Ω(5A)	17c	Hit	2SK1118, 2SK1404, 2SK1637
2SK2098-01M(MR)	MOS-N-FET-e	V-MOS, LogL, 150V, 20A, 50W, <0,1Ω(10A)	17c	Fjd	2SK1266, 2SK2377, 2SK2923
2SK2099-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 6A, 20W, <0,85Ω(5A)	30c$	Fjd	IRFR234A
2SK209-BL	N-FET	-	35	Tos	→2SK209
2SK209-GR	N-FET	-	35	Tos	→2SK209
2SK209-O	N-FET	-	35	Tos	→2SK209
2SK210	N-FET	FM/VHF, 18V, Idss>3mA, Up<3V	35c	Tos	2SK217
2SK2100(-01MR)	MOS-N-FET-e	V-MOS, 800V, 4A, 40W, <3,3Ω(5A)	17c	Fjd	2SK1808, 2SK1985
2SK2101-01M(MR)	MOS-N-FET-e	V-MOS, 800V, 6A, 50W, <2,1Ω(5A)	17c	Fujitsu	-
2SK2103	MOS-N-FET-e	V-MOS, LogL, 30V, 2A, <0,4Ω(5A)	39b	Rhm	2SK1311, 2SK1470, 2SK1717, 2SK2315
2SK2104(FS)	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W	30c$	Rhm	2SK1471, 2SK1719, 2SK1949
2SK2105	MOS-N-FET-e	V-MOS, 100V, 2A, 20W, <0,3Ω	30c$	Rhm	-
2SK2106	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 30W, <0,115Ω	17c	Rohm	BUK541-60, 2SK705, 2SK1255, 2SK1260
2SK2107	MOS-N-FET-e	V-MOS, 200V, 20A, 100W, <0,18Ω(10A)	30c$	Tos	2SK2136-Z
2SK2108	MOS-N-FET-e*	V-MOS, LogL, 250V, 6A, 25W, <0,5Ω(5A)	17c	Sanyo	-
2SK2109	MOS-N-FET-e*	V-MOS, LogL, 60V, ±0,5A, <0,8Ω(0,5A)	39b	Nec	2SK1079, 2SK1697
2SK210-BL	N-FET	-	35	Tos	→2SK210
2SK210-GR	N-FET	-	35	Tos	→2SK210
2SK210-Y	N-FET	-	35	Tos	→2SK210
2SK211	N-FET	FM/VHF, 18V, Idss>1mA, Up<4V	35c	Tos	2SK197
2SK2110	MOS-N-FET-e*	V-MOS, LogL, 100V, ±0,5A, <1,2Ω(0,5A)	39b	Nec	2SK1079, 2SK1728
2SK2111	MOS-N-FET-e*	V-MOS, LogL, 60V, ±1A<0,45Ω(0,5A)	39b	Nec	2SK1485, 2SK1726, 2SK1728
2SK2112	MOS-N-FET-e*	V-MOS, LogL, 100V, ±1A<0,8Ω(0,5A)	39b	Nec	2SK1485, 2SK1728
2SK2113	GaAs-N-FET-d	UHF, 3V, Idss=12..60mA, Up<2,5V	44z(2mm)	Nec	-
2SK2114	MOS-N-FET-e*	V-MOS, 450V, 5A, 35W, <1,4Ω(2,5A)	17c	Hit	2SK1231..32, 2SK1351, 2SK1608, 2SK1626
2SK2115	MOS-N-FET-e*	=2SK2114:500V, <1,5Ω(2,5A)	17c	Hit	2SK1232, 2SK1351, 2SK1608, 2SK1627,
2SK2116	MOS-N-FET-e*	V-MOS, 450V, 7A, 35W, <0,8Ω(5A)	17c	Hit	2SK1352, 2SK1566..67, 2SK1609, 2SK1805
2SK2117	MOS-N-FET-e*	=2SK2116:500V, <0,9e(5A)	17c	Hit	2SK1352, 2SK1567, 2SK1805
2SK2118	MOS-N-FET-e*	V-MOS, 600V, 5A, 35W, <1,5Ω(2,5A)	17c	Hit	2SK1118, 2SK1404, 2SK1637, 2SK2097,
2SK2119	MOS-N-FET-e*	=2SK1910:Iso, 30W	17c	Hit	2SK943, 2SK1095, 2SK1345..46, 2SK1307,
2SK211-GR	N-FET	-	35	Tos	→2SK211
2SK211-O	N-FET	-	35	Tos	→2SK211
2SK211-Y	N-FET	-	35	Tos	→2SK211
2SK212	N-FET	FM, 20V, Idss>0,6mA, Up<2,5V	40d	Sanyo	BF410A, 2N5484
2SK2120	MOS-N-FET-e*	=2SK1911:Iso, 35W	17c	Hit	2SK1257, 2SK1653
2SK2121	MOS-N-FET-e*	V-MOS, LogL, 60V, 50A, 100W, <10mΩ(20A)	18c$	Hit	BUK539-60, 2SK1258, 2SK1379

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2SK2122	MOS-N-FET-e	=2SK1478	17c	Mat	→2SK1478
2SK2123	MOS-N-FET-e	=2SK1605	17c	Mat	→2SK1605
2SK2124	MOS-N-FET-e	=2SK1606	17c	Mat	→2SK1606
2SK2125	MOS-N-FET-e	=2SK1833	17c	Mat	→2SK1833
2SK2126	MOS-N-FET-e	=2SK1608	17c	Mat	→2SK1608
2SK2127	MOS-N-FET-e	=2SK1609	17c	Mat	→2SK1609
2SK2128	MOS-N-FET-e	=2SK1834	17c	Mat	→2SK1834
2SK2129	MOS-N-FET-e	=2SK1846:	17c	Mat	2SK1356,2SK1460
2SK213	MOS-N-FET-e*	V-MOS,140V,0,5A,30W,8e,20/30nS	17d*	Hit	-
2SK2130	MOS-N-FET-e	=2SK1612	17c	Mat	→2SK1612
2SK2131	MOS-N-FET-e*	V-MOS,LogL,150V,±15A,35W,<0,12Ω(5A)	17c	Nec	2SK1266,2SK2098,2SK2377,2SK2923
2SK2132	MOS-N-FET-e*	V-MOS,180V,±4A,1,8W,<0,65Ω(5A)	78c	Nec	-
2SK2133	MOS-N-FET-e	V-MOS,250V,±16A,75W,<0,26Ω(5A)	17c$	Nec	BUZ255
2SK2133-Z	MOS-N-FET-e	=2SK2133:	30c$	-	2SK1636,2SK1636,2SK2063
2SK2134	MOS-N-FET-e	V-MOS,200V,±13A,70W,<0,4Ω(5A)	17c$	Nec	BUK456-200,BUZ255,IRF640,IRF642
2SK2134-Z	MOS-N-FET-e	=2SK2134:	30c$	-	2SK1636
2SK2135	MOS-N-FET-e	V-MOS,200V,±14A,35W,<0,18Ω(5A)	17c	Nec	2SK1350,2SK2012,2SK2382
2SK2136	MOS-N-FET-e	V-MOS,200V,±20A,75W,<0,18Ω(10A)	17c$	Nec	BUZ30A,IRF650A,2SK2918
2SK2136-Z	MOS-N-FET-e	=2SK2136:	30c$	-	2SK2107
2SK2137	MOS-N-FET-e	V-MOS,600V,±4A,30W,<2,4Ω(5A)	17c	Nec	2SK1637,2SK1404,2SK2097,2SK2118,..
2SK2138	MOS-N-FET-e	V-MOS,600V,±5A,70W,<2,4Ω(2,5A)	17c$	Nec	2SK1117,2SK1402,2SK1809,2SK1923
2SK2138-Z	MOS-N-FET-e	=2SK2138:	30c$	-	2SK1624,2SK2089,2SK1915
2SK2139	MOS-N-FET-e	V-MOS,600V,±5A,35W,<1,5Ω(2,5A)	17c	Nec	2SK1637,2SK1404,2SK2097,2SK2118,..
2SK214	MOS-N-FET-e*	=2SK213:160V	17d*	Hit	-
2SK2140	MOS-N-FET-e	V-MOS,600V,±7A,75W,<1,5Ω(3,5A)	17c$	Nec	BUK657-600,BUZ91,BUZ305
2SK2140-Z	MOS-N-FET-e	=2SK2140:	30c$	-	SSW7N60A,2SK1625,2SK2060,2SK2908
2SK2141	MOS-N-FET-e	V-MOS,600V,±6A,35W,<1,1Ω(5A)	17c	Nec	2SK1404,2SK2045,2SK2101,2SK2118
2SK2142	MOS-N-FET-e	V-MOS,LogL,250V,12A,70W,<0,35Ω	17c$	Sanyo	-
2SK2144	MOS-N-FET-e*	=2SK2059:Iso,25W	17c	Hit	2SK1572,2SK1767
2SK2145	N-FET	Dual,50V,Idss=1,2..14mA,Up<1,5V	45ba2	Tos	-
2SK2145-GR	N-FET	-	45	Tos	→2SK2145
2SK2145-L	N-FET	-	45	Tos	→2SK2145
2SK2146	MOS-N-FET-e	V-MOS,250V,2A,25W,<2Ω(5A)	17c	Tos	-
2SK2147(-01MR)	MOS-N-FET-e	V-MOS,900V,6A,80W,<2,8Ω(5A)	18c	Fjd	2SK1176,2SK1464,2SK1685,2SK1859..
2SK2148(-01)	MOS-N-FET-e	V-MOS,600V,12A,80W,<0,75Ω(5A)	18c	Fjd	2SK1405
2SK2149	MOS-N-FET-e*	V-MOS,500V,10A,125W,<0,8Ω(5A)	18c$	Tos	2SK724,2SK1488,2SK1753,2SK1785..
2SK215	MOS-N-FET-e*	=2SK213:180V	17d*	Hit	-
2SK2150	MOS-N-FET-e*	V-MOS,500V,15A,150W,<0,4Ω(5A)	18c$	Tos	BUZ338,2SK899,2SK1516,2SK1610,..
2SK2151	MOS-N-FET-e*	V-MOS,LogL,20V,1A,<0,75Ω(0,5A)	39b	Sanyo	2SK1485,2SK1726,2SK1728,2SK2111
2SK2152	MOS-N-FET-e*	V-MOS,LogL,20V,2A,<0,18Ω(5A)	39b	Sanyo	2SK1311,2SK1470,2SK1717,2SK2315
2SK2153	MOS-N-FET-e*	V-MOS,LogL,20V,4A,20W,<0,12Ω(5A)	30c$	Sanyo	2SK1059,2SK1112,2SK1471,2SK1719
2SK2154	MOS-N-FET-e*	V-MOS,LogL,20V,12A,30W,<58mΩ(5A)	30c$	Sanyo	-
2SK2156A	MOS-N-FET-e	V-MOS,LogL,60V,±25A,35W,<45mΩ(10A)	17c	Sanken	2SK1346,2SK1882,2SK1897,2SK2232..
2SK2157	MOS-N-FET-e	V-MOS,LogL,30V,±5A,<0,1Ω(2,5A)	39b	Nec	-
2SK2158	MOS-N-FET-e*	V-MOS,LogL,50V,±0,1A,<15Ω(10mA)	35a	Nec	2SK1590..91
2SK2159	MOS-N-FET-e*	V-MOS,LogL,60V,±2A,<0,3Ω(2,5A)	39b	Nec	2SK1311,2SK1470,2SK1717
2SK216	MOS-N-FET-e*	=2SK213:200V	17d*	Hit	-
2SK2160	MOS-N-FET-e*	V-MOS,LogL,200V,7A,25W,<0,45Ω(3,5A)	17c	Sanyo	BUK545-200,IRL5640A
2SK2161	MOS-N-FET-e*	V-MOS,LogL,200V,9A,25W,<0,35Ω(4,5A)	17c	Sanyo	IRLI640G,2SK3160
2SK2162	MOS-N-FET-e	V-MOS,180V,1A,20W	30c$	Tos	2SK1195,2SK1838
2SK2163	MOS-N-FET-e	V-MOS,LogL,60V,40A,40W,<20mΩ(20A)	17c	Sanyo	2SK1257,2SK1653,2SK1952
2SK2164	MOS-N-FET-e	V-MOS,LogL,60V,45A,70W,<20mΩ(20A)	30c$	Sanyo	2SK1919
2SK2165	MOS-N-FET-e*	V-MOS,LogL,60V,40A,100W,<50mΩ(20A)	18c$	Fjd	BUK539-60,2SK1379,2SK1297,2SK1514
2SK2166(-01)	MOS-N-FET-e*	=2SK2165:Iso,80W	18c	Fjd	2SK1298,2SK1666,2SK2203
2SK2167	MOS-N-FET-e*	V-MOS,250V,0,4A,<12Ω(0,5A)	39b	Sanyo	-
2SK2168	MOS-N-FET-e*	V-MOS,250V,0,8A,<5Ω(0,5A)	39b	Sanyo	-
2SK2169	MOS-N-FET-e*	V-MOS,250V,0,4A,<5Ω(0,5A)	9c	Sanyo	-
2SK217	N-FET	VHF,30V,Idss>2,5mA,Up<2,5V	35c	Hit	2SK210,2SK217
2SK2170	N-FET	30V,20mA,Idss>1,2mA,Up<2,5V	35a(1,6mm)	Sanyo	-
2SK2171	N-FET	40V,100mA,Idss>40mA,Up<5V	39b	Sanyo	-
2SK2171-3	N-FET	-	39	Sanyo	→2SK2171
2SK2171-4	N-FET	-	39	Sanyo	→2SK2171
2SK2171-5	N-FET	-	39	Sanyo	→2SK2171
2SK2173	MOS-N-FET-e*	V-MOS,LogL,60V,50A,125W,<17mΩ(20A)	18c$	Tos	BUK539-60,2SK1258,2SK1379,2SK2121,..

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2SK2174(L,S)	MOS-N-FET-e*	V-MOS, 500V, 20A, 120W, <0,27Ω(10A)	?30c$	Hit	-
2SK2175	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 30W, <0,13Ω(5A)	17c$	Hit	BUK552-60, 2SK971..72, 2SK1115, 2SK1910
2SK2176	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,5Ω(2,5A)	17c	Rohm	2SK1231..32, 2SK1351, 2SK1608
2SK2177	MOS-N-FET-e	V-MOS, 500V, 1A, 10W, <7Ω(0,5A)	30c$	Shi	2SK580, 2SK1152, 2SK1672, 2SK2017..
2SK2178	MOS-N-FET-e	V-MOS, 500V, 2A, 15W, <4Ω(5A), 40/70nS	30c$	Shi	MTD2N50
2SK2179	MOS-N-FET-e	V-MOS, 500V, 3A, 20W, <2,3Ω(1,5A)	30c$	Shi	2SK2059
2SK217-C	N-FET	-	35	Hit	→2SK217
2SK217-D	N-FET	-	35	Hit	→2SK217
2SK217-E	N-FET	-	35	Hit	→2SK217
2SK218	N-FET	Video-Camera, 15V, Idss>50mA	7d	Mat	-
2SK2180	MOS-N-FET-e	V-MOS, 500V, 3A, 40W, <2,3Ω(1,5A)	17c$	Shi	2SK1154, 2SK1244, 2SK1494
2SK2181	MOS-N-FET-e	=2SK2180:	30c$	Shi	2SK1314, 2SK1721, 2SK2066
2SK2182	MOS-N-FET-e	=2SK2180: Iso, 25W	17c	Shi	BUK445-500, 2SK1863, 2SK1572, 2SK1767..
2SK2183	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,5e, 55/100ns	17c$	Shi	BUZ41..42, IRF830, 2SK893, 2SK1246
2SK2184	MOS-N-FET-e	=2SK2183:	30c$	Shi	2SK1314, 2SK1722, 2SK2067, 2SK2356Z..
2SK2185	MOS-N-FET-e	=2SK2180: Iso, 30W	17c	Shi	2SK1232, 2SK1351, 2SK1608, 2SK2115..
2SK2186	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <1e, 70/140nS	17c$	Shi	2SK1503, 2SK2366
2SK2187	MOS-N-FET-e	=2SK2186:	30c$	Shi	2SK1865, 2SK2069, 2SK2366Z
2SK2188	MOS-N-FET-e	=2SK2186: Iso, 40W	17c	Shi	2SK2475
2SK2189	MOS-N-FET-e	=2SK2186: 70W	16c$	Shi	2SK724, 2SK896, 2SK1488, 2SK1753..
2SK2190	MOS-N-FET-e	=2SK2186: Iso, 40W	18c	Shi	2SK1206, 2SK1329, 2SK1523, 2SK1696..
2SK2191	MOS-N-FET-e	V-MOS, 500V, 12A, 60W, <0,7Ω(5A)	30c$	Shi	2SK1865, 2SK2187, 2SK2366Z
2SK2192	MOS-N-FET-e	=2SK2191: 80W	16c$	Shi	2SK899, 2SK1678, 2SK1745, 2SK1757
2SK2193	MOS-N-FET-e	=2SK2186: Iso, 50W	18c	Shi	2SK1269, 2SK1331, 2SK1524
2SK2194	MOS-N-FET-e	V-MOS, 500V, 15A, 110W, <0,45e, 110/270nS	16c$	Shi	2SK899, 2SK1610, 2SK1678, 2SK1745..
2SK2195	MOS-N-FET-e	=2SK2194: Iso, 60W	18c	Shi	2SK1269, 2SK1331, 2SK1524
2SK2196	MOS-N-FET-e	V-MOS, 500V, 20A, 125W, <0,35Ω(10A)	16c$	Shi	2SK1170, 2SK1411, 2SK1498, 2SK2057..
2SK2197	MOS-N-FET-e	=2SK2196: Iso, 70W	18c	Shi	2SK1406, 2SK1525
2SK2198	MOS-N-FET-e	V-MOS, 500V, 30A, 220W, <0,23Ω(10A)	77c$	Shi	2SK1520, 2SK1629, 2SK1971
2SK2199	MOS-N-FET-e*	V-MOS, 250V, 0,8A, 15W, <5Ω(0,5A)	30c$	Sanyo	IRFR215, 2SK1195, 2SK1838
2SK22	MOS-N-FET	-	-	-	-
2SK220	MOS-N-FET-e	V-MOS, 160V, 8A, 100W, <1,5Ω, 25/45nS	23e*	Hit	2SK258, (BUZ33)
2SK2200	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, 1,2W, <0,45Ω(5A)	?12	Tos	-
2SK2201	MOS-N-FET-e*	=2SK2200: 20W	30c$	Tos	2SK1113, 2SK1254, 2SK1284, 2SK1299
2SK2202	MOS-N-FET-e*	V-MOS, LogL, 120V, 7A, 20W, <0,4Ω(5A)	17c	Hit	BUK545-200, 2SK1957
2SK2203	MOS-N-FET-e*	=2SK2121: Iso, 60W	?18c	Hit	2SK1298, 2SK1424, 2SK1666
2SK2204(L,S)	MOS-N-FET-e*	=2SK2205:	30c$	Hit	2SK1792, 2SK1919
2SK2205	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 75W, <15mΩ(20A)	17c$	Hit	2SK1542, 2SK1911
2SK2206	MOS-N-FET-e*	=2SK2205: Iso, 35W	17c	Hit	2SK1257, 2SK1653, 2SK1952
2SK2207	MOS-N-FET-e	V-MOS, 900V, ±3A, 35W, <5Ω(1,5A)	17c	Sak	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK2208	MOS-N-FET-e	V-MOS, 900V, ±5A, 75W, <3Ω(2,5A)	18c	Sak	2SK1463, 2SK1684, 2SK1859, 2SK2147
2SK2209(-01R)	MOS-N-FET-e	V-MOS, 500V, 15A, 80W, <0,48e	18c	Fjd	2SK1269, 2SK1331, 2SK1405, 2SK1524
2SK221	MOS-N-FET-e	=2SK220: 200V	23e*	Hit	2SK258, (BUZ33)
2SK2210	MOS-N-FET-e	V-MOS, 750V, ±4A, 50W, <2,4Ω(5A)	17c	Matsushita	2SK1808, 2SK1985, 2SK2100..01
2SK2211	MOS-N-FET-e*	V-MOS, LogL, 30V, ±1A, <0,6Ω(0,5A), 12/220nS, int.Rgate	39b	Mat	(2SK1726, 2SK1728, 2SK2111..12)
2SK2212	MOS-N-FET-e*	V-MOS, 200V, 10A, 30W, <0,3Ω(5A)	17c	Hit	2SK526, 2SK1036, 2SK1762
2SK2213-01(L,S)	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,76Ω(5A)	30c$	Fjd	2SK2366Z
2SK2215-01(L,S)	MOS-N-FET-e	V-MOS, 600V, 8A, 80W, <1,2Ω(5A)	30c$	Fjd	-
2SK2216	MOS-N-FET-e	V-MOS, VHF-Pow, 60V, 20A, Pq=150W(860MHz)	-	Hit	-
2SK2217	MOS-N-FET-e	V-MOS, UHF-Pow, 60V, 10A, Pq=60W(860MHz)	-	Hit	-
2SK2218	N-FET	15V, 100mA, Idss>40mA, Up<4,5V	39b	Sanyo	-
2SK2218-3	N-FET	-	39	Sanyo	→2SK2218
2SK2218-4	N-FET	-	39	Sanyo	→2SK2218
2SK2218-5	N-FET	-	39	Sanyo	→2SK2218
2SK2219	N-FET	Cond.-Microphone, 20V, Idss>0,14mA	35f(2mm)	Sanyo	-
2SK2219-21	N-FET	-	35(2mm)	Sanyo	→2SK2219
2SK2219-22	N-FET	-	35(2mm)	Sanyo	→2SK2219
2SK2219-23	N-FET	-	35(2mm)	Sanyo	→2SK2219
2SK222	N-FET	GenP, LN, 40V, Idss>0,6mA, Up=0,5V	7e	Sanyo	2SK68, 2SK102, 2SK184
2SK2220	MOS-N-FET-e*	V-MOS, AF-Pow, 180V, 8A, 100W, 250/90nS	18d*	Hit	-
2SK2221	MOS-N-FET-e*	=2SK2220: 200V	18d*	Hit	-
2SK2222	MOS-N-FET-e	V-MOS, 800V, 5A, 80W, <2,2Ω(5A)	16c	Tos	2SK1684, 2SK1774..75, 2SK1859, 2SK2147
2SK2223-01(R)	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,76Ω(5A)	18c	Fjd	2SK1206, 2SK1329, 2SK1523, 2SK1696..
2SK2224-01(R)	MOS-N-FET-e	V-MOS, 900V, 3A, 50W, <4Ω(1,5A)	18c	Fjd	2SK1463, 2SK1683, 2SK1859, 2SK2147..

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2SK2225	MOS-N-FET-e*	V-MOS, 1500V, 2A, 50W, <12Ω(5A)	16c	Hit	-
2SK2226(-01)L,S	MOS-N-FET-e	V-MOS, LogL, 150V, 20A, 80W, <0,1Ω	30c$	Fjd	-
2SK2227	MOS-N-FET-e	V-MOS, 600V, 4A, 60W, <2,4Ω	30c$	Sanyo	-
2SK2228	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, <0,11Ω(2,5A)	?12c	Tos	(2SK1112, 2SK1471, 2SK1719, 2SK1949)
2SK2229	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, <0,3Ω(1,5A)	?12c	Tos	(2SK1112, 2SK1471, 2SK1719)
2SK223	N-FET	AF-Driver, 80V, Idss>1,2mA, Up=0,75V	7e	Sanyo	-
2SK2230	MOS-N-FET-e	V-MOS, 250V, 2A, 1,2W, <2Ω(5A)	?12c	Tos	-
2SK2231	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,3Ω(1,5A)	30c$	Tos	2SK1112, 2SK1471, 2SK1719, 2SK1949
2SK2232	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 35W, <80mΩ(10A)	17c	Tos	2SK1095, 2SK1214, 2SK1346, 2SK1897
2SK2233	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <55mΩ(10A)	18c$	Tos	2SK1297, 2SK1514, 2SK1665, 2SK2096
2SK2234	MOS-N-FET-e*	V-MOS, 500V, ±8A, 40W, <0,6Ω(5A)	17c	Nec	2SK1352, 2SK1567, 2SK1609, 2SK1805
2SK2235	MOS-N-FET-e	V-MOS, 250V, 2A, 20W, <2Ω(1,5A)	30c$	Tos	2SK2250
2SK2236	MOS-N-FET-e*	V-MOS, 500V, 5A, 40W, <1,6Ω(2,5A)	17c	Tos	2SK1232, 2SK1351, 2SK1608, 2SK1627..
2SK2237	MOS-N-FET-e*	V-MOS, 500V, 7A, 45W, <0,8Ω(5A)	17c	Tos	2SK1352, 2SK1567, 2SK1805, 2SK2117..
2SK2238	MOS-N-FET-e	V-MOS, 450V, 1,5A, 30W, <3,5Ω(0,5A)	17c	Sak	BUK444-450, 2SK1833, 2SK1988..89..
2SK2239	MOS-N-FET-e	V-MOS, 450V, 3A, 35W, <2Ω(1,5A)	17c	Sak	BUK445-450, 2SK1862..63, 2SK2431..
2SK2240	MOS-N-FET-e	V-MOS, 450V, 5A, 35W, <1,5(2,5A)	17c	Sak	2SK1351, 2SK1445, 2SK1990..91..
2SK2241	MOS-N-FET-e	V-MOS, 450V, 7A, 35W, <0,95(3,5A)	17c	Sak	2SK1446, 2SK2116..17, 2SK2237..
2SK2242	MOS-N-FET-e	V-MOS, 450V, 7A, 70W, <0,95(3,5A)	18c	Sak	2SK1451
2SK2243	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,75(5A)	18c	Sak	2SK1328..29, 2SK1523, 2SK1831..32..
2SK2244	MOS-N-FET-e	V-MOS, 450V, 12A, 85W, <0,55(5A)	18c	Sak	2SK1268..69, 2SK1331, 2SK1453, 2SK1524..
2SK2245	MOS-N-FET-e	V-MOS, 450V, 15A, 85W, <0,45(7,2A)	18c	Sak	2SK1268..69, 2SK1331, 2SK1453, 2SK1524..
2SK2247	MOS-N-FET-e*	V-MOS, LogL, 60V, ±2A, <0,35Ω(2,5A)	39b	Hit	2SK1311, 2SK1717, 2SK1763, 2SK2315,..
2SK2248-01L,S	MOS-N-FET-e	V-MOS, LogL, 30V, 10A, 20W, <0,08Ω	30c$	Fjd	2SK2018, 2SK2329, 2SK2414
2SK2249-01L,S	MOS-N-FET-e	V-MOS, LogL, 30V, 10A, 35W, <0,08Ω(5A)	30c$	Fjd	2SK2041, 2SK2282, 2SK3082
2SK225	MOS-N-FET-e	V-MOS, 120V, 7A, 100W, <1,7Ω, 180/60nS	20d*	Hit	(2SK343..344)
2SK2250-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 2A, 10W, <2Ω(5A)	30c$	Fjd	2SK2235, 2SK2530
2SK2251-01	MOS-N-FET-e	V-MOS, 250V, 2A, 20W, <2Ω(5A)	17c$	Fjd	2SK923
2SK2252-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 8A, 50W, <0,5Ω(5A)	30c$	Fjd	IRFW634A, MTB9N25E, 2SK1621, 2SK2252
2SK2253-01M(MR)	MOS-N-FET-e	V-MOS, 250V, 8A, 40W, <0,5Ω(5A)	17c	Fjd	2SK1568..69, 2SK1668, 2SK1987, 2SK2425..
2SK2254-01(L,S)	MOS-N-FET-e	V-MOS, 250V, 18A, 80W, <0,18Ω(5A)	30c$	Fjd	2SK2063, 2SK2133Z
2SK2255-01M(MR)	MOS-N-FET-e	=2SK2254: Iso, 50W	17c	Fjd	2SK1818, 2SK2012, 2SK2711
2SK2256-01	MOS-N-FET-e	=2SK2254	17c$	Fjd	IRF654A, IRF2525, 2SK2133
2SK2257-01	MOS-N-FET-e	V-MOS, 500V, 17A, 150W, <0,4Ω(5A)	18c$	Fjd	IRFP460, 2SK1411, 2SK2057, 2SK2837..
2SK2258-01	MOS-N-FET-e	V-MOS, 1000V, 4A, 100W, <3,6Ω(5A)	18c$	Fjd	BUZ357..358, 2SK1205, 2SK1359, 2SK1773
2SK2259-01M(MR)	MOS-N-FET-e	V-MOS, LogL, 60V, 40A, 40W, <30mΩ(20A)	17c	Fujitsu	2SK1257, 2SK1653, 2SK1952, 2SK2120
2SK226	MOS-N-FET-e	=2SK225: 140V	20d*	Hit	(2SK343..344)
2SK2260	MOS-N-FET-e*	V-MOS, 150V, 1,2A, <2,2Ω(0,5A)	39b	Sanyo	2SK1334, 2SK2992
2SK2261	MOS-N-FET-e	V-MOS, 60V, 2A, 1,2W	78c	Rhm	2SK462, 2SK973, 2SK1763, 2SK1973
2SK2262	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, 1,2W, <0,35Ω(5A)	78c	Rhm	2SK973, 2SK1282, 2SK1763, 2SK1950
2SK2263	MOS-N-FET-e	V-MOS, 500V, 5A, 80W	16c	Rhm	2SK1206, 2SK1523
2SK2264	MOS-N-FET-e*	V-MOS, 350V, 5A, 100W, <3Ω(5A)	18d*	Hit	-
2SK2265	MOS-N-FET-e*	=2SK2264: 400V	18c$	Hit	BUZ330..331, 2SK501
2SK2266	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 65W, <55mΩ(10A)	30c$	Tos	2SK1792, 2SK1919, 2SK2164, 2SK2376
2SK2267	MOS-N-FET-e*	V-MOS, LogL, 60V, 60A, 150W, <15mΩ(30A)	77c$	Tos	2SK1223, 2SK1259, 2SK1380
2SK2268	N-FET	=2SK2270: SMD	35d(2mm)	Sanyo	-
2SK2269	N-FET	=2SK2270: SMD	35f(3mm)	Sanyo	-
2SK227	MOS-N-FET-e	=2SK225: 160V	20d*	Hit	(2SK344)
2SK2270	N-FET	15V, 30mA, 0,3W, Idss=1,2..12mA	40f	Sanyo	-
2SK2272-01R	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω	18c	Fjd	2SK1176, 2SK1464, 2SK1684, 2SK1859..
2SK2273	MOS-N-FET-e*	V-MOS, LogL, 20V, 0,5A, <0,75Ω	35a	Sanyo	2SK1847, 2SK3287
2SK2274	MOS-N-FET-e	V-MOS, 700V, 5A, 45W, <1,7Ω(5A)	17c	Toshiba	2SK1808, 2SK1985, 2SK2101
2SK2275	MOS-N-FET-e*	V-MOS, 900V, ±3,5A, 35W, <2,8Ω(5A)	17c	Nec	2SK1356, 2SK1460, 2SK1808, 2SK1995
2SK2276	MOS-N-FET-e	V-MOS, LogL, 60V, ±3A, 10W, <0,2Ω(3A), 29/150nS, int. Rgate	30c$	Mat	2SK1282, 2SK1254, 2SK1299, 2SK1950, +
2SK2277	MOS-N-FET-e*	V-MOS, LogL, 60V, ±1A, <0,85Ω(0,5A), 35/210nS, int. Rgate	39b	Mat	(2SK1485, 2SK1726, 2SK1728, 2SK2111)
2SK2278(L,S)	MOS-N-FET-e	=2SK1317:	?30c$	Hit	-
2SK2279	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, 15W, <0,35Ω(5A)	30c$	Shi	2SK973, 2SK1763
2SK2280	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,16Ω(2,5A)	30c$	Shi	2SK1471, 2SK1719, 2SK1949, 2SK2231
2SK2281	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 25W, <0,1Ω(5A)	30c$	Shi	MTD12N06EZL, 2SK2018, 2SK2414
2SK2282	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 40W, <0,1Ω(5A)	30c$	Shi	2SK1907, 2SK2041
2SK2283	MOS-N-FET-e*	=2SK2282: Iso, 30W	17c	Shi	2SK1033, 2SK1093, 2SK1344, 2SK1895..
2SK2284	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <0,07Ω(7,2A)	30c$	Shi	2SK1648, 2SK1898, 2SK1967, 2SK2322
2SK2285	MOS-N-FET-e*	=2SK2284: Iso, 35W	17c	Shi	2SK1094, 2SK1286, 2SK1896, 2SK2462
2SK2286	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 60W, <45mΩ(10A)	30c$	Shi	2SK1622, 2SK1918, 2SK1967, 2SK2311

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2SK2287	MOS-N-FET-e*	=2SK2286: Iso, 40W	17c	Shi	2SK1095, 2SK1345, 2SK1897, 2SK1951..
2SK2288	MOS-N-FET-e*	V-MOS, LogL, 60V, 30A, 70W, <30mΩ(10A)	30c$	Shi	MTP35N06ZL, 2SK1792, 2SK1900, 2SK2411-Z
2SK2289	MOS-N-FET-e*	=2SK2288: Iso, 50W	17c	Shi	2SK1653, 2SK1952, 2SK2120, 2SK2498..
2SK2290	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 75W, <20mΩ(22,5A)	30c$	Shi	2SK1792, 2SK1919, 2SK2164, 2SK2266..
2SK2291	MOS-N-FET-e*	=2SK2290: Iso, 55W	17c	Shi	2SK1653, 2SK1952, 2SK2120, 2SK2312..
2SK2292-01L,S	MOS-N-FET-e	V-MOS, 250V, 4A, 20W, <1,1Ω(5A)	30c$	Fjd	MTD5N25E, 2SK1920, 2SK2099
2SK2293	MOS-N-FET-e	V-MOS, 900V, 3A, 30W	17c	Ehm	2SK1356, 2SK1460
2SK2294	MOS-N-FET-e	V-MOS, 800V, 3A, 30W, <4Ω(1,5A)	17c	Rhm	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK2295	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,4Ω(5A)	17c	Rhm	2SK1118, 2SK2044, 2SK2100..01, 2SK2118..
2SK2298	MOS-N-FET-e	V-MOS, 500V, 7A, 30W	17c	Rohm	2SK1352, 2SK1567, 2SK1609, 2SK1805..
2SK2299(N)	MOS-N-FET-e	V-MOS, 450V, 7A, 30W, <1,1Ω(5A)	17c	Rhm	2SK1352, 2SK1566, 2SK1609, 2SK1805..
2SK23(A)-2..-9	N-FET	FM/VHF, 18..40V, Idss>2,7mA, Up<4,9V	10a	Son	2SK107, 2SK192
2SK2300	MOS-N-FET-e	V-MOS, LogL, 60V, 15A, 30W	17c	Rohm	2SK943, 2SK1286, 2SK1345
2SK2306(FS)	MOS-N-FET-e	V-MOS, LogL, 60V, 3A, 20W	30c$	Rhm	2SK1113, 2SK1254, 2SK1282
2SK2307(FS)	MOS-N-FET-e	V-MOS, LogL, 100V, 2A, 20W	30c$	Rhm	2SK1113, 2SK1299, 2SK1254, 2SK1284..
2SK2308	MOS-N-FET-e	V-MOS, 60V, 3A, <0,15e	30c$	Rhm	2SK1282, 2SK1254, 2SK1299, 2SK1950..
2SK2309	MOS-N-FET-e	V-MOS, LogL, 100V, 10A, 30W	17c	Hit	BUK545-100, 2SK1035, 2SK1305, 2SK1904..
2SK2310	MOS-N-FET-e	V-MOS, 60V, 15A, 60W, <45me	30c$	Rhm	2SK1648, 2SK1898, 2SK2322
2SK2311	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 40W, <80mΩ(10A)	30c$	Tos	2SK1622, 2SK1918, 2SK2286, 2SK2938
2SK2312	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 45W, <25mΩ(20A)	17c	Tos	2SK1257, 2SK1653, 2SK1952, 2SK2120
2SK2313	MOS-N-FET-e*	V-MOS, LogL, 60V, 60A, 150W, <15mΩ(30A)	18c$	Tos	BUK539-60, 2SK1258, 2SK1379, 2SK2121
2SK2314	MOS-N-FET-e*	V-MOS, LogL, 100V, 27A, 75W, <130mΩ(15A	17c$	Tos	2SK1293, 2SK2050
2SK2315	MOS-N-FET-e*	V-MOS, LogL, 60V, ±2A, <0,45Ω(2,5A)	39b	Hit	2SK1311, 2SK1470, 2SK1717, 2SK2055
2SK2316	MOS-N-FET-e*	V-MOS, LogL, 20V, 2A, <0,2Ω(5A)	39b	Sanyo	2SK1311, 2SK1470, 2SK1717, 2SK2315
2SK2317	MOS-N-FET-e*	V-MOS, LogL, 20V, 4A, 20W, <85mΩ(5A)	30c$	Sanyo	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK2318	MOS-N-FET-e*	V-MOS, LogL, 20V, 12A, 30W, <38mΩ(5A)	30c$	Sanyo	2SK1754, 2SK2018, 2SK2414, 2SK3023
2SK2319	MOS-N-FET-e	V-MOS, 800V, 7A, 90W, <1,7Ω(3,5A)	16c	Tos	2SK1464, 2SK1685, 2SK1774..75
2SK2320	MOS-N-FET-e	V-MOS, 800V, 8,5A, 90W, <1,2Ω(5A)	16c	Tos	2SK1464, 2SK1686, 2SK1775, 2SK2148
2SK2321	MOS-N-FET-e	V-MOS, 250V, 12A, 70W, <0,35Ω(5A)	30c$	Sanyo	2SK1636, 2SK2063
2SK2322(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 50W, <50mΩ(5A)	30c$	Hit	2SK1648, 2SK1898
2SK2323	MOS-N-FET-e	V-MOS, 600V, ±1A40W, <8,5Ω(0,5A)	17c	Mat	BUK444-600, 2SK808
2SK2324	MOS-N-FET-e	V-MOS, 600V, ±2A, 40W, <6Ω(5A)	17c	Mat	BUK445-600, 2SK1758, 2SK1834, 2SK2043..
2SK2325	MOS-N-FET-e	V-MOS, 600V, ±3A, 40W, <2,5Ω(5A)	17c	Mat	2SK1572, 2SK1767, 2SK1995, 2SK2144..
2SK2326	MOS-N-FET-e	V-MOS, 600V, ±5A, 50W, <1,5Ω(5A)	17c	Mat	2SK2100..01, 2SK2044, 2SK2097, 2SK2118..
2SK2327	MOS-N-FET-e	V-MOS, 600V, ±10A, 100W, <0,75©(5A)	18c	Mat	2SK1686, 2SK2148
2SK2328	MOS-N-FET-e	=2SK1403A: 7A, 75W	17c$	Hit	-
2SK2329(L,S)	MOS-N-FET-e	V-MOS, LogL, 30V, 10A, 20W, <40mΩ(5A)	30c$	Hit	2SK2414
2SK2330	MOS-N-FET-e*	=2SK1168:	?30c$	Hit	-
2SK2331	GaAs-N-FET-d	SHF, 3V, Idss=25..120mA, Up<2V, 12GHz	52za	Tos	-
2SK2332	GaAs-N-FET-d	SHF, 3V, Idss=20..80mA, Up<2V, 12GHz	52za	Tos	-
2SK2333	MOS-N-FET-e	V-MOS, 700V, 6A, 50W, <2Ω(5A), 70/160nS	17c	Shidengen	2SK2101, 2SK1985
2SK2334(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 30W, <55mΩ(10A)	30c$	Hit	MTD20N06HDL, 2SK2782
2SK2339	MOS-N-FET-e*	V-MOS, LogL, 80±10V, ±10A, 30W, <0,23Ω, 500/2800nS, int.Rgate, Z-Di(S→D)	30c$	Mat	-
2SK2340	MOS-N-FET-e	V-MOS, 900V, ±5A, 50W, <2,8Ω(5A)	17c	Mat	2SK1808, 2SK1985
2SK2341	MOS-N-FET-e	V-MOS, 250V, n11A, 35W, <0,26Ω(5A)	17c	Nec	2SK1036, 2SK1762, 2SK2011, 2SK2426
2SK2342	MOS-N-FET-e*	V-MOS, LogL, 30V, ±2A, <0,35Ω(1A), 40/280nS, int.Rgate	30c$	Mat	(2SK973, 2SK1763)
2SK2343	MOS-N-FET-e	V-MOS, LogL, 20V, 6A, 2W, <60mΩ	6-MDIP	Sanyo	-
2SK2344	MOS-N-FET-e*	V-MOS, 20V, 7A, 2W, <35mΩ(5A)	6-MDIP	Sanyo	-
2SK2345	MOS-N-FET-e*	V-MOS, 350V, 6A, 35W, <0,8Ω(5A)	17c	Hit	BUK445-400, 2SK1351, 2SK1608, 2SK1627..
2SK2346	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 25W, <50mΩ(10A)	17c	Hit	2SK1095, 2SK1214, 2SK1345, 2SK1897
2SK2347	MOS-N-FET-e	V-MOS, 1000V, 20A, 160W, <0,8Ω(10A)	?77c	Sanyo	-
2SK2348	MOS-N-FET-e	V-MOS, 1200V, 14A, 160W, <1,5Ω(5A)	?77c	Sanyo	-
2SK2349	MOS-N-FET-e	V-MOS, 1500V, 10A, 160W, <2,5Ω(5A)	?77c	Sanyo	-
2SK2350	MOS-N-FET-e*	V-MOS, 200V, 8,5A, 30W, <0,4Ω(5A)	17c	Tos	BUK545-200, 2SK1668, 2SK2160..61..
2SK2351	MOS-N-FET-e	V-MOS, 600V, 6A, 100W, <1,25Ω(5A)	17c$	Tos	BUZ91, 2SK1117, 2SK1924
2SK2352	MOS-N-FET-e	=2SK2351: Iso	17c	Tos	2SK1118, 2SK1404, 2SK2045
2SK2353	MOS-N-FET-e	=2SK2355: Iso, ±4,5A, 30W	17c	Nec	2SK1351, 2SK1608, 2SK2114..15, 2SK2236..
2SK2354	MOS-N-FET-e	=2SK2356: Iso, ±4,5A, 30W	17c	Nec	2SK1351, 2SK1608, 2SK2115, 2SK2236..
2SK2355	MOS-N-FET-e	V-MOS, 450V, ±5A, 50W, <1,4Ω(2,5A)	17c$	Nec	2SK1156, 2SK1246, 2SK1440, 2SK1751
2SK2355-Z	MOS-N-FET-e	=2SK2355:	30c$	-	2SK1313..1314, 2SK1540..1541, 2SK2042,..
2SK2356	MOS-N-FET-e	=2SK2355: 500V, <1,5Ω(2,5A)	17c$	Nec	2SK1156, 2SK1246, 2SK1751
2SK2356-Z	MOS-N-FET-e	=2SK2356:	30c$	-	2SK1314, 2SK1316, 2SK1541, 2SK2991..
2SK2357	MOS-N-FET-e	=2SK2359: Iso, ±6A, 35W	17c	Nec	2SK1352, 2SK1805, 2SK2116..17, 2SK2237..
2SK2358	MOS-N-FET-e	=2SK2360: Iso, ±6A, 35W	17c	Nec	2SK1352, 2SK1805, 2SK2117, 2SK2237..

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2SK2359	MOS-N-FET-e	V-MOS, 450V, ±7A, 75W, <0,9e(5A)	17c$	Nec	2SK1495..96, 2SK1574, (IRF840, IRF842)
2SK2359-Z	MOS-N-FET-e	=2SK2359:	30c$	-	2SK1315..16, 2SK1540..1541
2SK2360	MOS-N-FET-e	=2SK2359: 500V, 1Ω(5A)	17c$	Nec	2SK1496, 2SK1574, (IRF840, IRF842)
2SK2360-Z	MOS-N-FET-e	=2SK2360:	30c$	-	2SK1316, 2SK1541, 2SK1864, 2SK2776..
2SK2361	MOS-N-FET-e	V-MOS, 450V, ±10A, 100W, <0,9e(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1784..85,..
2SK2362	MOS-N-FET-e	=2SK2361: 500V, <1Ω(5A)	18c$	Nec	2SK644, 2SK724, 2SK1488, 2SK1785..
2SK2363	MOS-N-FET-e	V-MOS, 450V, ±8A, 35W, <0,5Ω(5A)	17c	Nec	2SK1352, 2SK1805, 2SK2116..17, 2SK2237..
2SK2364	MOS-N-FET-e	=2SK2363: 500V, <0,6Ω(5A)	17c	Nec	2SK1352, 2SK1609, 2SK2117, 2SK2237..
2SK2365	MOS-N-FET-e	V-MOS, 450V, ±10A, 75W, <0,5Ω(5A)	17c$	Nec	2SK1442, 2SK1503
2SK2365-Z	MOS-N-FET-e	=2SK2365:	30c$	-	2SK1865, 2SK2187, 2SK2191, 2SK2889
2SK2366	MOS-N-FET-e	=2SK2365: 500V, <0,6Ω(5A)	17c$	Nec	2SK1503, 2SK2186
2SK2366-Z	MOS-N-FET-e	=2SK2366:	30c$	-	2SK1865, 2SK2187, 2SK2191, 2SK2889
2SK2367	MOS-N-FET-e	V-MOS, 450V, ±15A, 120W, <0,5Ω(5A)	18c$	Nec	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK2368	MOS-N-FET-e	=2SK2367: 500V, <0,6Ω(5A)	18c$	Nec	2SK725, 2SK788, 2SK899, 2SK1610, 2SK1745
2SK2369	MOS-N-FET-e	V-MOS, 450V, ±20A, 120W, <0,35Ω(10A)	18c$	Nec	2SK870, 2SK1409, 2SK1411, 2SK1497..1500+
2SK2370	MOS-N-FET-e	=2SK2369: 500V, <0,4Ω(10A)	18c$	Nec	2SK870, 2SK1409, 2SK1411, 2SK1498/1500..
2SK2371	MOS-N-FET-e	V-MOS, 450V, ±25A, 160W, <0,25Ω(10A)	18c$	Nec	2SK1499..1500
2SK2372	MOS-N-FET-e	=2SK2371: 500V, <0,27Ω(10A)	18c$	Nec	2SK1500
2SK2373	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,2A, <1,4Ω(10mA), integr. Rgate	35a	Hit	(2SK1590..91)
2SK2374	MOS-N-FET-e	V-MOS, 900V, ±5A, 100W, <2,8Ω(5A)	18c	Mat	2SK1176, 2SK1464, 2SK1684, 2SK1859..
2SK2375	MOS-N-FET-e	V-MOS, 900V, ±8A, 100W, <1,7Ω(5A)	18c	Mat	2SK1365, 2SK1464, 2SK1685, 2SK1775
2SK2376	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 100W, <25mΩ(20A)	30c$	Tos	2SK1792, 2SK1919, 2SK2164, 2SK2266
2SK2377	MOS-N-FET-e	V-MOS, LogL, 170V, ±20A, 50W, <0,145Ω	17c	Mat	-
2SK2378	MOS-N-FET-e*	V-MOS, 200V, 13A, 30W, <0,21Ω(5A)	17c	Sanyo	IRFS650A, 2SK1350, 2SK2135, 2SK2382
2SK2379	MOS-N-FET-e*	V-MOS, 200V, 20A, 40W, <95mΩ(10A)	17c	Sanyo	2SK1818, 2SK2560, 2SK3162, 2SK3262-..
2SK238	N-FET	FM, 20V, Idss>0,5mA, Up<2,5V	35e	Nec	BF510
2SK2380	N-FET	-	35(1,6mm)	Mat	→2SK2380
2SK2380-Q:	N-FET	-	35(1,6mm)	Mat	→2SK2380
2SK2380-R:	N-FET	-	35(1,6mm)	Mat	→2SK2380
2SK2380-S:	N-FET	-	35(1,6mm)	Mat	→2SK2380
2SK2381	MOS-N-FET-e*	V-MOS, 200V, 5A, 25W, <0,8Ω(2,5A)	17c	Tos	BUK444-200, BUZ73, 2SK2010, 2SK2108
2SK2382	MOS-N-FET-e*	V-MOS, 200V, 15A, 45W, <0,18Ω(10A)	17c	Tos	2SK1350, 2SK2012, 2SK2135
2SK2383	MOS-N-FET-e	V-MOS, 500V, n13A, 100W, <0,6Ω(5A)	18c	Mat	2SK1269, 2SK1331, 2SK1405, 2SK1524
2SK2384	MOS-N-FET-e	V-MOS, LogL, 30V, 6A, <0,07Ω(5A)	6-MQIP	Sanyo	-
2SK2385	MOS-N-FET-e*	V-MOS, LogL, 60V, 36A, 40W, <55mΩ(10A)	17c	Tos	2SK1257, 2SK1952, 2SK2120, 2SK2312
2SK2386	MOS-N-FET-e	V-MOS, 500V, 5A, 75W, <1,6Ω(2,5A)	17c$	Tos	BUZ41..42, 2SK553, 2SK893, 2SK1246..
2SK2388	MOS-N-FET-e	V-MOS, 600V, 3,5A, 40W, <2,2Ω(1,5A)	17c	Tos	2SK1118, 2SK2044, 2SK2097, 2SK2118
2SK2389	MOS-N-FET-e	V-MOS, 700V, 5A, 125W, <1,7Ω(5A)	17c$	Tos	-
2SK238-K14	N-FET	-	35	Nec	→2SK238
2SK238-K15	N-FET	-	35	Nec	→2SK238
2SK238-K16	N-FET	-	35	Nec	→2SK238
2SK238-K17	N-FET	-	35	Nec	→2SK238
2SK2390	MOS-N-FET-e*	V-MOS, LogL, 60V, 12A, 20W, <90mΩ(5A)	17c	Sanyo	2SK1093, 2SK1256, 2SK1305..06, 2SK1344..
2SK2391	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 35W, <130mΩ(10A)	17c	Tos	2SK1266, 2SK1307, 2SK1292, 2SK1906..
2SK2393	MOS-N-FET-e*	V-MOS, 1500V, 8A, 200W, <2,8Ω(5A)	77c$	Hit	-
2SK2394	N-FET	-	35	Sanyo	→2SK2394
2SK2394-5	N-FET	-	35	Sanyo	→2SK2394
2SK2394-6	N-FET	-	35	Sanyo	→2SK2394
2SK2394-7	N-FET	-	35	Sanyo	→2SK2394
2SK2395	N-FET	HF, 15V, Idss=6..32mA, Up<1,5V	40a	Sanyo	BC264C..D
2SK2396A	MOS-N-FET-e	V-MOS, Dual, UHF-L, 60V, 15A, 290W, PQ>90W(860MHz, 50V)	-	Nec	-
2SK2397(-01MR)	MOS-N-FET-e	V-MOS, 800V, 5A, 50W, <2,3Ω(2,5A)	17c	Fjd	2SK1808, 2SK1985, 2SK2101
2SK2398	MOS-N-FET-e*	V-MOS, 60V, 45A, 100W, <30mΩ(20A)	18c$	Tos	2SK1297, 2SK1514, 2SK1665, 2SK2096..
2SK2399	MOS-N-FET-e*	V-MOS, LogL, 100V, 5A, 20W, <33mΩ(2,5A)	30c$	Tos	2SK1474, 2SK1804, 2SK2013
2SK24	N-FET	AF/AM, 40V, Idss=0,6..24mA, Up<6V	?2a	Sanyo	BFS71, 2N3822, 2N5457, 2SK246, 2SK330..
2SK240	N-FET	Dual, 40V, Idss>2,6mA, Up<1,5V	7e+7a	Tos	-
2SK2400	MOS-N-FET-e*	=2SK2399: 1,3W	?12	Tos	-
2SK2401	MOS-N-FET-e*	V-MOS, 200V, 15A, 45W, <0,18Ω(10A)	30c$	Tos	2SK1636, 2SK2063, 2SK2133Z, 2SK2254
2SK2402	MOS-N-FET-e	V-MOS, 600V, 3,5A, 75W, <2,2Ω(1,5A)	17c$	Tos	BUZ90, 2SK1117, 2SK1809, 2SK1923..
2SK2403	MOS-N-FET-e	FREDFET, 450V, 3A, 50W, <3,2Ω(1,5A)	30c$	Sanyo	-
2SK2404	MOS-N-FET-e	FREDFET, 450V, 5A, 60W, <1,6Ω(5A)	30c$	Sanyo	-
2SK2405	MOS-N-FET-e	FREDFET, 450V, 10A, 70W, <0,75Ω(5A)	30c$	Sanyo	-
2SK2406	MOS-N-FET-e	FREDFET, 450V, 1A, 30W, <4,5Ω(0,5A)	30c$	Sanyo	-
2SK2407	MOS-N-FET-e	FREDFET, 450V, 10A, 70W, <0,75Ω(5A)	17c$	Sanyo	-

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2SK2408	MOS-N-FET-e*	V-MOS, 500V, 7A, 60W, <0,9e(5A)	17c$	Hit	2SK1496, 2SK1574, (IRF840, IRF842)
2SK2409	MOS-N-FET-e*	V-MOS, LogL, 60V, ±45A, 35W, <27mΩ(20A)	17c	Nec	2SK1653, 2SK1952, 2SK2120, 2SK2312..
2SK241	MOS-N-FET-d*	FM/VHF, 20V, Idss>1,5mA, Up<2,5V	41d	Tos	-
2SK2410	MOS-N-FET-e*	=2SK2411: Iso, 35W	17c	Nec	2SK1262
2SK2411	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 75W, <60mΩ(10A)	17c$	Nec	2SK1291, 2SK1296, 2SK2930
2SK2411Z	MOS-N-FET-e*	=2SK2411:	30c$	-	2SK1900
2SK2412	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 30W, <70mΩ(10A)	17c	Nec	2SK1095, 2SK1214, 2SK1345, 2SK1882..
2SK2413	MOS-N-FET-e*	=2SK2414: 1,8W	78c	Nec	-
2SK2414(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±10A, 20W, <0,07Ω(5A	30c$	Nec	MTD12N06EZL, MTD305SEL, VL, 2SK2018
2SK2415(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±8A, 20W, <0,1Ω(5A)	30c$	Nec	2SK1472, 2SK1475, 2SK1748
2SK2417	MOS-N-FET-e*	V-MOS, 250V, 7,5A, 30W, <0,5Ω(3,5A)	17c	Tos	2SK1036, 2SK1762, 2SK2011, 2SK2425..26..
2SK2418(L,S)	MOS-N-FET-e*	V-MOS, LogL, 50V, 7A, 20W, <0,05Ω(5A)	30c$	Hit	2SK1472, 2SK1475, 2SK1748
2SK2419	MOS-N-FET-e	V-MOS, 60V, ±22A, 35W, <50mΩ(10A)	17c	Sak	2SK1290, 2SK1346, 2SK1882, 2SK1897..
2SK242	N-FET	FM/VHF, 20V, Idss>0,6mA, Up<2,5V	35e	Sanyo	BF510, 2SK238
2SK2420	MOS-N-FET-e	V-MOS, 60V, ±30A, 40W, <28mΩ(10A)	17c	Sak	2SK1421, 2SK2120, 2SK2289, 2SK2312..
2SK2421	MOS-N-FET-e	V-MOS, 60V, ±40A, 40W, <20mΩ(20A)	17c	Sak	2SK1421, 2SK2120, 2SK2291, 2SK2312..
2SK2422	MOS-N-FET-e*	V-MOS, 650V, 4A, 20W, <2,6Ω(5A)	17c	Hit	2SK1637, 2SK1404, 2SK2097, 2SK2118..
2SK2423	MOS-N-FET-e*	V-MOS, 450V, 7A, 35W, <0,7Ω(5A)	17c	Hit	2SK1352, 2SK1566..67, 2SK1609, 2SK1805..
2SK2424	MOS-N-FET-e*	V-MOS, 450V, 8A, 35W, <0,55Ω(5A)	17c	Hit	2SK1352, 2SK1566..67, 2SK1609, 2SK1805..
2SK2425	MOS-N-FET-e*	V-MOS, 250V, 7A, 30W, <0,55Ω(5A)	17c	Hit	2SK1478, 2SK1568..69, 2SK1668
2SK2426	MOS-N-FET-e*	V-MOS, 250V, 12A, 35W, <0,35Ω(5A)	17c	Hit	2SK1036, 2SK1762
2SK2428	MOS-N-FET-e	V-MOS, 100V, 10A, 30W, <0,14Ω	17c	Rhm	BUK545-100, 2SK1230, 2SK1305, 2SK1430..
2SK2429	MOS-N-FET-e	V-MOS, 30V, 3A, 1,2W, <0,125e	78c	Rhm	(2SK974, 2SK1282, 2SK1299, 2SK1950,..)
2SK242-T3	N-FET	-	35	Sanyo	→2SK242
2SK242-T4	N-FET	-	35	Sanyo	→2SK242
2SK242-T5	N-FET	-	35	Sanyo	→2SK242
2SK2430	MOS-N-FET-e	V-MOS, 30V, 3A, 20W, <0,125e	30c$	Rhm	2SK974, 2SK1282, 2SK1299, 2SK1950..
2SK2431	MOS-N-FET-e*	V-MOS, 450V, 3A, 25W, <2,8Ω(5A)	17c	Hit	BUK445-450, 2SK1572, 2SK1767
2SK2432	MOS-N-FET-e	V-MOS, LogL, 30V, 35A, 50W, <25mΩ(10A)	-	Sanyo	-
2SK2433	MOS-N-FET-e	V-MOS, LogL, 60V, 30A, 50W, <40mΩ(10A)	-	Sanyo	-
2SK2434	MOS-N-FET-e	V-MOS, 450V, 5A, 40W, <1,4Ω(5A)	-	Sanyo	-
2SK2435	MOS-N-FET-e	V-MOS, 800V, 3,5A, 40W, <3,6Ω(1,5A)	-	Sanyo	-
2SK2436	MOS-N-FET-e	V-MOS, 800V, 7A, 50W, <1,8Ω(3,5A)	-	Sanyo	-
2SK2437	MOS-N-FET-e*	V-MOS, 30V, 2A, <0,18Ω(5A)	39b	Sanyo	2SK1311, 2SK1717, 2SK2103, 2SK2748..
2SK2438	MOS-N-FET-e	V-MOS, 30V, 4A, 20W, <80mΩ(5A)	30c$	Sanyo	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK2439	MOS-N-FET-e	V-MOS, 30V, 12A, 30W, <40mΩ(5A)	30c$	Sanyo	MTD1206EZL, 2SK1754, 2SK2018, 2SK2414
2SK2440	MOS-N-FET-e*	V-MOS, LogL, 20V, 6A, 2W, <38mΩ(5A)	8-MDIP/ca1	Sanyo	-
2SK2441	MOS-N-FET-e*	V-MOS, LogL, 20V, 7A, 2W, <32mΩ(5A)	8-MDIP/ca1	Sanyo	-
2SK2442	MOS-N-FET-e*	V-MOS, LogL, 30V, 7A, 2W, <48mΩ(4A)	8-MDIP/ca1	Sanyo	-
2SK2445	MOS-N-FET-e*	V-MOS, 60V, 50A, 125W, <18mΩ(20A)	18c$	Tos	BUK539-60, 2SK1258, 2SK1379, 2SK2121,..
2SK2446(-01)L,S	MOS-N-FET-e	V-MOS, LogL, 100V, 30A, 80W, <70mΩ	30c$	Fjd	2SK2789, 2SK3084
2SK2459(N)	MOS-N-FET-e	V-MOS, 200V, 5A, 30W, <0,65Ω(2,5A)	17c	Rhm	BUK444-200, BUZ73, 2SK2010, 2SK2108
2SK246	N-FET	GenP, 50V, Idss>1,2mA, Up<6V	7e	Tos	2N5457, 2SK330
2SK2460(N)	MOS-N-FET-e	V-MOS, 250V, 5A, 30W, <0,75Ω(2,5A)	17c	Rhm	2SK2010, 2SK2108
2SK2461	MOS-N-FET-e*	V-MOS, LogL, 100V, ±20A, 35W, <80mΩ(10A)	17c	Nec	2SK1292, 2SK1348, 2SK1906, 2SK2098..
2SK2462	MOS-N-FET-e*	V-MOS, LogL, 100V, ±15A, 30W, <14mΩ(5A)	17c	Nec	2SK1288, 2SK1306, 2SK1558, 2SK2131
2SK2463	MOS-N-FET-e	V-MOS, LogL, 60V, 2A, <0,38Ω(5A)	39b	Rhm	2SK1273, 2SK1470, 2SK1717, 2SK2315..
2SK2464	MOS-N-FET-e	V-MOS, 30V, 45A, 50W, <12mΩ(20A)	-	Sanyo	-
2SK2466	MOS-N-FET-e*	V-MOS, LogL, 100V, 30A, 40W, <70mΩ(10A)	17c	Tos	2SK1262, 2SK2577, 2SK2954
2SK2467	MOS-N-FET-e	V-MOS, 180V, 9A, 80W	16c	Tos	-
2SK2469-01MR	MOS-N-FET-e	V-MOS, 300V, 5A, 30W, <1Ω(2,5A)	17c	Fjd	BUK445-400, IRFS740, 2SK1377, 2SK2345
2SK247	N-FET	HF, 15V, Idss>0,5mA, Up<3V	35f	Mat	-
2SK2470-01MR	MOS-N-FET-e	V-MOS, 300V, 10A, 40W, <0,53Ω(5A)	17c	Fjd	2SK2924, 2SK2960
2SK2471-01	MOS-N-FET-e	V-MOS, 300V, 10A, 80W, <0,53Ω(5A)	18c$	Fjd	BUZ325, BUZ326, IRFP340
2SK2473-01MR	MOS-N-FET-e	V-MOS, 300V, 20A, 125W, <0,2Ω(10A)	18c$	Fjd	2SK868, IRFP360, 2SK1674
2SK2474	MOS-N-FET-e	V-MOS, 250V, ±2A, 10W, <2Ω(5A)	30c$	Mat	2SK2235, 2SK2250
2SK2475	MOS-N-FET-e	V-MOS, 500V, 12A, 50W, <0,7Ω(5A)	17c	Shidengen	2SK2842
2SK2476	MOS-N-FET-e	V-MOS, 800V, ±3A, 40W, <5Ω(5A)	17c	NEC	2SK1356, 2SK1460, 2SK1995
2SK2477	MOS-N-FET-e	V-MOS, 800V, ±10A, 150W, <1Ω(5A)	18c$	Nec	2SK1796, 2SK1933
2SK2478	MOS-N-FET-e	V-MOS, 900V, ±2A, 30W, <7,5Ω(5A)	17c	Nec	2SK1143, 2SK1174, 2SK1459, 2SK1994
2SK2479	MOS-N-FET-e	V-MOS, 900V, ±3A, 70W, <7,5Ω(5A)	17c$	Nec	2SK1456, 2SK1601, 2SK1638, 2SK1793
2SK2480	MOS-N-FET-e	V-MOS, 900V, ±3A, 35W, <4Ω(5A)	17c	Nec	2SK1356, 2SK1460, 2SK1995
2SK2481	MOS-N-FET-e	V-MOS, 900V, ±4A, 70W, <4Ω(5A)	17c$	Nec	2SK1457, 2SK1639, 2SK1643, 2SK1807..
2SK2482	MOS-N-FET-e	V-MOS, 900V, ±5A, 100W, <4Ω(5A)	18c$	Nec	2SK727, 2SK1341, 2SK1760, 2SK1794..

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2SK2483	MOS-N-FET-e	V-MOS, 900V, ±3,5A, 40W, <2,8Ω(5A)	17c	Nec	2SK1460, 2SK1808, 2SK1985
2SK2484	MOS-N-FET-e	V-MOS, 900V, ±5A, 75W, <2,8Ω(5A)	17c$	Nec	2SK1501, 2SK1639, 2SK1643, 2SK1807..
2SK2485	MOS-N-FET-e	V-MOS, 900V, ±6A, 100W, <2,8Ω(5A)	18c$	Nec	2SK1502, 2SK1614, 2SK1692, 2SK1795..
2SK2486	MOS-N-FET-e	V-MOS, 900V, ±7A, 120W, <2Ω(5A)	18c$	Nec	2SK1358, 2SK1462, 2SK1692, 2SK1795..
2SK2487	MOS-N-FET-e	V-MOS, 900V, ±8A, 140W, <1,6Ω(5A)	18c$	Nec	2SK1358, 2SK1462, 2SK1692, 2SK1795..
2SK2488	MOS-N-FET-e	V-MOS, 900V, ±10A, 150W, <1,2Ω(5A)	18c$	Nec	2SK1796, 2SK1933
2SK2489	MOS-N-FET-e	V-MOS, 180V, 10A, 45W, <0,25Ω(5A)	30c$	Shi	2SK1636, 2SK2088, 2SK2133-Z, 2SK2254..
2SK2490	MOS-N-FET-e	=2SK2489: Iso, 40W	17c	Shi	2SK2011, 2SK2212, 2SK2426, 2SK2508
2SK2491	MOS-N-FET-e	V-MOS, 180V, 20A, 70W, <0,13Ω(10A)	30c$	Shi	2SK2107, 2SK2136-Z
2SK2492	MOS-N-FET-e	=2SK2491: Iso, 70W	17c	Shi	2SK1818
2SK2493	MOS-N-FET-e*	V-MOS, LogL, 16V, 5A, 20W, <0,1Ω(2,5A)	30c$	Tos	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK2494	MOS-N-FET-e	V-MOS, 60V, 2A, 20W, 0,3e	30c$	Rhm	-
2SK2494-01	MOS-N-FET-e	V-MOS, 60V, 45A, 80W, <25me	17c$	Fjd	2SK1418, 2SK1542, 2SK1911
2SK2495	MOS-N-FET-e	V-MOS, 250V, ±2A, 30W, <2Ω(5A)	30c$	Mat	-
2SK2496	GaAs-N-FET	SHF, 12GHz	-	Tos	-
2SK2497	GaAs-N-FET	SHF, 12GHz	-	Tos	-
2SK2498	MOS-N-FET-e*	=2SK2499: Iso, 35W	17c	Nec	2SK1257, 2SK1653, 2SK2120, 2SK2529
2SK2499	MOS-N-FET-e*	V-MOS, LogL, 60V, ±50A, 75W, <14mΩ(20A)	17c$	Nec	BUK556-60, MTP52N06VL, 2SK2049
2SK2499-Z	MOS-N-FET-e*	=2SK2499	30c$	-	2SK2553
2SK25	N-FET	AM/FM, 18V, Idss=0,6..24mA, Up<7,2V	??a	Sanyo	BF244..245, BFS71, 2N3822..23..
2SK2503	MOS-N-FET-e	V-MOS, LogL, 60V, 5A, 20W, <0,135Ω	30c$	Rhm	2SK1112, 2SK1719, 2SK1949, 2SK2231
2SK2504	MOS-N-FET-e	V-MOS, LogL, 100V, 5A, 20W, <0,22Ω	30c$	Rhm	2SK1474, 2SK1804, 2SK2016, 2SK2399
2SK2505	MOS-N-FET-e	V-MOS, 120V, 5A, 20W, <0,2Ω	30c$	Rhm	2SK1920
2SK2507	MOS-N-FET-e*	V-MOS, LogL, 50V, 25A, 30W, <80mΩ(5A)	17c	Tos	2SK1882, 2SK1897, 2SK2232, 2SK2346..
2SK2508	MOS-N-FET-e*	V-MOS, 250V, 13A, 45W, <0,25Ω(6,5A)	17c	Tos	2SK2012, 2SK2255, 2SK2711
2SK2509	MOS-N-FET-e	V-MOS, 500V, ±2,5A, 40W, <4Ω(1,5A)	30c$	Mat	2SK1690
2SK2510	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 35W, <20mΩ(20A)	17c	Nec	2SK1653, 2SK2120, 2SK2529
2SK2511	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 80W, <27mΩ(20A)	18c$	Nec	BUK539-60, 2SK2121, 2SK2173, 2SK2313,..
2SK2512	MOS-N-FET-e*	=2SK2513: Iso, 35W	17c	Nec	2SK1653, 2SK2120, 2SK2529
2SK2513	MOS-N-FET-e*	V-MOS, LogL, 60V, ±45A, 75W, <23mΩ(20A)	17c$	Nec	BUK556-60, 2SK1542, 2SK1911, 2SK2931
2SK2513-Z	MOS-N-FET-e*	=2SK2513	30c$	-	2SK1919, 2SK2164, 2SK2266, 2SK2376
2SK2514	MOS-N-FET-e*	V-MOS, LogL, 60V, ±50A, 150W, <15mΩ(20A)	18c$	Nec	BUK539-60, 2SK2121, 2SK2173, 2SK2313,..
2SK2515	MOS-N-FET-e*	V-MOS, LogL, 60V, ±50A, 150W, <9mΩ(20A)	18c$	Nec	BUK539-60, 2SK2121, 2SK2173, 2SK2313,..
2SK2516-01L,S	MOS-N-FET-e	V-MOS, 30V, 50A, 80W, <13me	30c$	Fjd	2SK2553
2SK2517-01L,S	MOS-N-FET-e	V-MOS, 60V, 50A, 80W, <20me	30c$	Fjd	2SK2553
2SK2518-01MR	MOS-N-FET-e	V-MOS, 200V, 20A, 50W, <0,13Ω(10A)	17c	Fjd	2SK1818, 2SK2560
2SK2519-01	MOS-N-FET-e	V-MOS, 200V, 10A, 40W, <0,4Ω(5A)	17c$	Fjd	2SK890, 2SK1221, 2SK1393, 2SK1761..
2SK2520-01MR	MOS-N-FET-e	V-MOS, 200V, 10A, 30W, <0,4Ω(5A)	17c	Fjd	IRLI640G, 2SK2011, 2SK2212, 2SK2426
2SK2521-01	MOS-N-FET-e	V-MOS, 200V, 18A, 50W, <0,18Ω(5A)	17c$	Fjd	BUZ30A, IRF3315, 2SK2136
2SK2522-01MR	MOS-N-FET-e	V-MOS, 200V, 18A, 40W, <0,18Ω	17c	Fjd	2SK1818
2SK2523-01	MOS-N-FET-e	V-MOS, 450V, 9A, 50W, <1Ω(4,5A)	17c$	Fjd	2SK1442, 2SK1503, 2SK2365..66
2SK2524-01MR	MOS-N-FET-e	V-MOS, 450V, 9A, 40W, <1e	17c	Fjd	2SK2363..64
2SK2525-01	MOS-N-FET-e	V-MOS, 450V, 9A, 80W, <1e	18c$	Fjd	2SK1488, 2SK1516, 2SK1753, 2SK1785..
2SK2526-01	MOS-N-FET-e	V-MOS, 900V, 5A, 60W, <3,6Ω(2,5A)	17c$	Fjd	2SK1457, 2SK1643, 2SK1807, 2SK2484..
2SK2527-01MR	MOS-N-FET-e	V-MOS, 900V, 5A, 40W, <3,6Ω(2,5A)	17c	Fjd	2SK1808, 2SK1985, 2SK2671
2SK2528-01	MOS-N-FET-e	V-MOS, 900V, 5A, 80W, <3,6Ω	18c$	Fjd	2SK727, 2SK1461, 2SK1760, 2SK1794..
2SK2529	MOS-N-FET-e*	V-MOS, LogL, 60V, 50A, 35W, <0,01Ω(20A)	17c	Tos	2SK1653, 2SK2120, 2SK2498, 2SK2512
2SK2530	MOS-N-FET-e	FREDFET, 250V, 2A, 20W, <2Ω(5A)	30c$	Sanyo	-
2SK2531	MOS-N-FET-e	FREDFET, 250V, 6A, 30W, <0,8Ω(5A)	-	Sanyo	-
2SK2532	MOS-N-FET-e	FREDFET, 250V, 10A, 40W, <0,39Ω(5A)	-	Sanyo	-
2SK2533	MOS-N-FET-e	FREDFET, 250V, 13A, 45W, <0,27Ω(5A)	-	Sanyo	-
2SK2534	MOS-N-FET-e	FREDFET, 250V, 16A, 50W, <0,18Ω(5A)	-	Sanyo	-
2SK2537	MOS-N-FET-e	V-MOS, 400V, 0,2A, <2,5e, 50/-nS	39b	Mat	-
2SK2538	MOS-N-FET-e	V-MOS, 250V, ±2A, 30W, <2Ω(5A)	17c	Mat	2SK2146
2SK2539	N-FET	FM/VHF, 15V, Idss=10..50mA, Up<3V	35f	Sanyo	-
2SK2539-6	N-FET	-	35	Sanyo	→2SK2539
2SK2539-7	N-FET	-	35	Sanyo	→2SK2539
2SK2539-8	N-FET	-	35	Sanyo	→2SK2539
2SK2540	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, <0,16Ω(5A)	78c	Rhm	(2SK1620, 2SK1741, 2SK1907)
2SK2541	MOS-N-FET-e*	V-MOS, LogL, 50V, ±0,1A, <20mΩ(10mA)	41c	Rhm	BS170, BSS98, 2SK1398
2SK2542	MOS-N-FET-e*	V-MOS, 500V, 8A, 80W, <0,85Ω(5A)	17c$	Tos	IRF840, 2SK1496, 2SK1574, 2SK2360
2SK2543	MOS-N-FET-e*	=2SK2542: Iso, 40W	17c	Tos	2SK1352, 2SK1609, 2SK2117, 2SK2237..
2SK2544	MOS-N-FET-e*	V-MOS, 600V, 6A, 80W, <1,25Ω(5A)	17c$	Tos	BUZ91, 2SK1117, 2SK1924, 2SK2140
2SK2545	MOS-N-FET-e*	=2SK2544: Iso, 40W	17c	Tos	2SK1118, 2SK1637, 2SK2097, 2SK2045..

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2SK2549	MOS-N-FET-e*	V-MOS, LogL, 16V, 2A, <0,29Ω(2,5A)	39b	Tos	-
2SK2550	MOS-N-FET-e*	V-MOS, 50V, 45A, 100W, <30mΩ(20A)	18c$	Tos	BUZ347, 2SK1998, 2SK2096, 2SK2233..
2SK2551	MOS-N-FET-e*	V-MOS, 50V, 50A, 150W, <11mΩ(20A)	18c$	Tos	BUZ346, 2SK1423, 2SK2121, 2SK2173..
2SK2552	N-FET	Condensator-Microphone, 20V, Idss>40?A	35b(1,6mm)	Nec	-
2SK2552-J2	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2552-J3	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2552-J4	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2552-J5	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2552-J6	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2552-J7	N-FET	-	35(1,6mm)	Nec	→2SK2552
2SK2553(L,S)	MOS-N-FET-e*	=2SK2529: 75W	30c$	Hit	2SK2499-Z
2SK2554	MOS-N-FET-e*	V-MOS, LogL, 60V, 75A, 150W, <6mΩ(45A)	18c$	Hit	-
2SK2555	MOS-N-FET-e	V-MOS, 30V, 6A, 30W, <40mΩ(5A)	30c$	Sanyo	2SK1472, 2SK1748, 2SK2415
2SK2556	MOS-N-FET-e*	V-MOS, 30V, 6A, 2W, <78mΩ(5A)	8-MDIP/ca1	Sanyo	-
2SK2557	MOS-N-FET-e*	V-MOS, 30V, 7A, 2W, <60mΩ(5A)	8-MDIP/ca1	Sanyo	-
2SK2559	MOS-N-FET-e	V-MOS, 200V, 10A, 40W, <0,22Ω	17c	Shi	2SK1036, 2SK1762, 2SK2011, 2SK2212..
2SK2560	MOS-N-FET-e	V-MOS, 200V, 20A, 60W, <0,1Ω	17c	Shi	2SK1266..67, 2SK2098, 2SK2377
2SK2561-01R	MOS-N-FET-e	V-MOS, 600V, 9A, 80W, <1,2Ω	18c	Fjd	2SK2148
2SK2562-01R	MOS-N-FET-e	V-MOS, 800V, 7A, 80W, <2,2Ω	18c	Fjd	2SK1464, 2SK1685, 2SK1774..75
2SK2563	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,2Ω(5A)	17c	Shi	2SK1118, 2SK2044, 2SK2118, 2SK2137..
2SK2564	MOS-N-FET-e	V-MOS, 600V, 8A, 30W, <1,2Ω(5A)	17c	Shi	..2SK2645, 2SK2740
2SK2568	MOS-N-FET-e*	V-MOS, Sw, Pow, 500V, 12A, 100W, <0,6Ω(5A)	18c$	Hit	2SK724, 2SK1488, 2SK1723, 2SK1785..
2SK2569	MOS-N-FET-e*	V-MOS, LogL, 50V, 0,2A, <2,6Ω(0,1A), integr. Rgate	35a	Hit	-
2SK2570	MOS-N-FET-e*	V-MOS, LogL, 20V, 0,2A, <1,1Ω, integr. Rgate	35a	Hit	-
2SK2571	MOS-N-FET-e	V-MOS, 450V, n13A, 100W, <0,45Ω(5A)	18c	Mat	2SK1268..69, 2SK1331, 2SK1524..25
2SK2572	MOS-N-FET-e	V-MOS, 500V, ±15A, 100W, <0,5Ω(5A)	18c	Mat	2SK1269, 2SK1331, 2SK1524..25
2SK2573	MOS-N-FET-e	V-MOS, 500V, ±20A, 100W, <0,4Ω(10A)	18c	Mat	2SK1406, 2SK1525
2SK2574	MOS-N-FET-e	V-MOS, LogL, 60V, ±20A, 45W, <70mΩ(10A)	17c	Matsushita	2SK1095, 2SK1290, 2SK1897, 2SK1951..
2SK2575	MOS-N-FET-e	V-MOS, LogL, 100V, ±15A, 45W, <135mΩ(5A)	17c	Mat	2SK1288, 2SK1306, 2SK1558, 2SK2131
2SK2576	MOS-N-FET-e	V-MOS, 250V, ±10A, 50W, <0,3Ω(5A)	17c	Mat	2SK1036, 2SK1762, 2SK2011, 2SK2426
2SK2577	MOS-N-FET-e	V-MOS, LogL, 100V, ±30A, 45W, <70mΩ(10A)	17c	Mat	2SK1262, 2SK2466
2SK2578	MOS-N-FET-e	V-MOS, LogL, 60V, ±5A, 30W, <0,2Ω(5A)	17c	Matsushita	BUK541-60, 2SK705, 2SK1255
2SK2579	MOS-N-FET-e	V-MOS, LogL, 60V, ±10A, 40W, <0,11Ω(5A)	17c	Matsushita	2SK1093, 2SK1256, 2SK1344, 2SK1895..
2SK258	MOS-N-FET-e	V-MOS, 250V, 8A, 125W, <1,3Ω, 25/140nS	23e*	Hit	(2SK277..278, 2SK293, 2SK299)
2SK2580	MOS-N-FET-e	V-MOS, LogL, 60V, ±40A, 45W, <35mΩ(20A)	17c	Matsushita	2SK1653, 2SK1952, 2SK2120, 2SK2312..
2SK2581	MOS-N-FET-e	V-MOS, LogL, 100V, ±5A, 30W, <0,47Ω(5A)	17c	Mat	BUK542-100, 2SK992, 2SK1260, 2SK1265
2SK2582	MOS-N-FET-e*	V-MOS, 350V, 13A, 75W, <0,4Ω(5A)	17c$	Hit	-
2SK2586	MOS-N-FET-e*	V-MOS, LogL, 60V, 60A, 125W, <10mΩ(30A)	18c$	Hit	BUK539-60, 2SK1258, 2SK1379, 2SK2121
2SK2588	MOS-N-FET-e	V-MOS, LogL, 150V, ±3A, 30W, <1,1Ω(5A)	17c	Mat	2SK1264
2SK259	MOS-N-FET-e	V-MOS, 350V, 5A, 125W, <3e, 25/140nS	23e*	Hit	(BUZ44, BUZ46, BUZ63)
2SK2590	MOS-N-FET-e*	V-MOS, 200V, 7A, 50W, <0,45Ω(5A)	17c$	Hit	BUZ30..32, BUZ73, 2SK741, 2SK1319
2SK2591	MOS-N-FET-e*	V-MOS, Sw, Pow, 500V, 8A, 35W, <0,6Ω(5A)	17c	Hit	2SK1532, 2SK1567, 2SK1805, 2SK2117..
2SK2592	MOS-N-FET-e	FREDFET, 250V, 13A, 60W, <0,27Ω(5A)	30c$	Sanyo	-
2SK2593	N-FET	-	35(1,6mm)	Mat	→2SK2593
2SK2593-P	N-FET	-	35(1,6mm)	Mat	→2SK2593
2SK2593-Q	N-FET	-	35(1,6mm)	Mat	→2SK2593
2SK2593-R	N-FET	-	35(1,6mm)	Mat	→2SK2593
2SK2593-S	N-FET	-	35(1,6mm)	Mat	→2SK2593
2SK2595	MOS-N-FET-e*	V-MOS, 17V, 1,1A, Pq>37,3dBm(836,5MHz)	-	Hit	-
2SK2596	MOS-N-FET-e*	V-MOS, 17V, 0,4A, Pq>30,2dBm(836,5MHz)	39b	Hit	-
2SK2597	MOS-N-FET-e	V-MOS, Dual, UHF-L, 60V, 15A, 290W, PQ>80W(960MHz, 30V)	-	Nec	-
2SK2598	MOS-N-FET-e*	V-MOS, 250V, 13A, 60W, <0,25Ω(6,5A)	30c$	Tos	2SK2063, 2SK2133Z, 2SK2254
2SK2599	MOS-N-FET-e*	V-MOS, 500V, 2A, 1,3W, <3,2Ω(5A)	?12	Tos	-
2SK260	MOS-N-FET-e	V-MOS, 400V, 5A, 125W, <3e, 25/140nS	23e*	Hit	(BUZ44, BUZ46, BUZ63)
2SK2601	MOS-N-FET-e*	V-MOS, 500V, 10A, 125W, <1Ω(5A)	18c$	Tos	2SK1488, 2SK1723, 2SK1745, 2SK1757..
2SK2602	MOS-N-FET-e*	V-MOS, 600V, 6A, 125W, <1,25Ω(5A)	18c$	Tos	2SK1032, 2SK1358, 2SK1502, 2SK1614..
2SK2603	MOS-N-FET-e*	V-MOS, 800V, 3A, 100W, <3,6Ω(1,5A)	17c$	Tos	BUK456-800, 2SK1456, 2SK1638, 2SK1600
2SK2604	MOS-N-FET-e*	V-MOS, 800V, 5A, 125W, <2,2Ω(5A)	18c$	Tos	2SK793..94, 2SK1341, 2SK1650, 2SK1794,..
2SK2605	MOS-N-FET-e*	V-MOS, 800V, 5A, 45W, <2,2Ω(5A)	17c	Tos	BUZ81, 2SK1457, 2SK1643, 2SK1807..
2SK2606	MOS-N-FET-e*	V-MOS, 800V, 8A, 85W, <1,2Ω(5A)	16c	Tos	2SK1774, 2SK1775, 2SK2847, 2SK2675..
2SK2607	MOS-N-FET-e*	V-MOS, 800V, 9A, 150W, <1,2Ω(5A)	18c$	Tos	2SK1796, 2SK1933, 2SK2078, 2SK2477
2SK2608	MOS-N-FET-e*	V-MOS, 900V, 3A, 100W, <4,3Ω(1,5A)	17c$	Tos	BUK456-1000, 2SK1456, 2SK1638, 2SK1793..
2SK261	N-FET	?2SK213	-	Hit	→2SK213
2SK2610	MOS-N-FET-e*	V-MOS, 900V, 5A, 125W, <2,5Ω(5A)	18c$	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..

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2SK2611	MOS-N-FET-e*	V-MOS, 900V, 9A, 150W, <1,4Ω(5A)	18c$	Tos	2SK1796, 2SK1933, 2SK2488, 2SK2676..
2SK2614	MOS-N-FET-e*	V-MOS, LogL, 50V, 20A, 40W, <80mΩ(5A)	30c$	Tos	IRLR2705, SPD21N05L, 2SK2334, 2SK2782
2SK2615	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,44Ω(5A)	39b	Tos	2SK1311, 2SK1717, 2SK1763, 2SK2315..
2SK2616	MOS-N-FET-e	V-MOS, 500V, 2A, 30W, <4Ω(5A)	30c$	Sanyo	IRFR420(A), MTD2N50E, 2SK2715
2SK2617(LS)	MOS-N-FET-e	V-MOS, 500V, 4A, 25W, <1,6Ω(5A)	17c	Sanyo	2SK1351, 2SK1232, 2SK1608, 2SK1627..
2SK2618(LS)	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,25Ω(5A)	17c	Sanyo	2SK1351, 2SK1232, 2SK1608, 2SK1627..
2SK2619	MOS-N-FET-e	V-MOS, 500V, 6A, 70W, <1,25Ω(5A)	30c$	Sanyo	2SK1496Z, 2SK1541, 2SK2356Z, 2SK2360Z,..
2SK262	N-FET	?2SK213	-	Hit	→2SK213
2SK2620	MOS-N-FET-e	V-MOS, 500V, 7A, 35W, <0,8Ω(4,5A)	17c	Sanyo	2SK1352, 2SK1567, 2SK1805, 2SK2117
2SK2621	MOS-N-FET-e	V-MOS, 500V, 12A, 120W, <0,6Ω(5A)	18c$	Sanyo	2SK1488, 2SK1723, 2SK1745, 2SK1757..
2SK2622	MOS-N-FET-e	V-MOS, 500V, 14A, 125W, <0,52Ω(5A)	18c$	Sanyo	2SK1610, 2SK1678, 2SK1745, 2SK1757
2SK2623	MOS-N-FET-e	V-MOS, 600V, 1,5A, 30W, <5,5Ω(0,5A)	30c$	Sanyo	IRFRC20, 2SK1880, 2SK2040, 2SK2865
2SK2624(LS)	MOS-N-FET-e	V-MOS, 600V, 3A, 25W, <2,6Ω(1,5A)	17c	Sanyo	2SK1572, 2SK1767, 2SK2044, 2SK2144
2SK2625(LS)	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2Ω(2,5A)	17c	Sanyo	2SK1637, 2SK2044, 2SK2097, 2SK2118..
2SK2626	MOS-N-FET-e	V-MOS, 600V, 5A, 70W, <2Ω(2,5A)	30c$	Sanyo	2SK1624, 2SK1915, 2SK2089, 2SK2777
2SK2627	MOS-N-FET-e	V-MOS, 600V, 5A, 40W, <2Ω(2,5A)	-	Sanyo	-
2SK2628(LS)	MOS-N-FET-e	V-MOS, 600V, 6A, 35W, <1,2Ω(5A)	17c	Sanyo	2SK1118, 2SK1404, 2SK2045, 2SK2118..
2SK2629	MOS-N-FET-e	V-MOS, 600V, 10A, 120W, <1Ω(5A)	18c$	Sanyo	BUZ334, 2SK1723, 2SK1968, 2SK2699
2SK263	N-FET	?2SK213	-	Hit	→2SK213
2SK2630	MOS-N-FET-e	V-MOS, 600V, 12A, 125W, <0,8Ω(5A)	18c$	Sanyo	BUZ334, 2SK1573, 2SK1723, 2SK1968
2SK2631	MOS-N-FET-e	V-MOS, 800, 1A, 30W, <10e(0,5A)	30c$	Sanyo	MTD1N80E, 2SK1533, 2SK2663
2SK2632(LS)	MOS-N-FET-e	V-MOS, 800V, 2,5A, 25W, <4,8Ω(1,5A)	17c	Sanyo	2SK1611, 2SK2294, 2SK2476
2SK2633(LS)	MOS-N-FET-e	V-MOS, 800V, 3A, 30W, <3,6Ω(1,5A)	17c	Sanyo	2SK1356, 2SK1460, 2SK1808, 2SK1995
2SK2634	MOS-N-FET-e	V-MOS, 800V, 3,5A, 70W, <3,6Ω(1,5A)	30c$	Sanyo	2SK1510, 2SK1528, 2SK1659, 2SK1858..
2SK2635	MOS-N-FET-e	V-MOS, 800V, 3,5A, 40W, <3,6Ω(2,5A)	-	Sanyo	-
2SK2636	MOS-N-FET-e	V-MOS, 800V, 7A, 50W, <1,8Ω(3,5A)	-	Sanyo	-
2SK2637	MOS-N-FET-e*	V-MOS, 20V, 8A, 2W, <25mΩ(5A)	8-MDIP/ca1	Sanyo	-
2SK2638-01MR	MOS-N-FET-e	V-MOS, 450V, 10A, 50W, <0,65Ω(5A)	17c	Fjd	2SK2475, 2SK2702, 2SK2714, 2SK2842..
2SK2639-01	MOS-N-FET-e	=2SK2638: 100W	18c$	Fjd	BUZ339, 2SK1488, 2SK2361, 2SK2362..
2SK264	N-FET	?2SK214	-	Hit	→2SK214
2SK2640-01MR	MOS-N-FET-e	V-MOS, 500V, 10A, 50W, <0,9Ω(5A)	17c	Fujitsu	2SK2475, 2SK2714, 2SK2842, 2SK3183
2SK2641-01	MOS-N-FET-e	=2SK2640: 100W	18c$	Fjd	BUZ339, 2SK1488, 2SK1753, 2SK1785..
2SK2643-01	MOS-N-FET-e	V-MOS, 500V, 15A, 125W, <0,55Ω(7,2A)	18c$	Fjd	IRFP450, 2SK1610, 2SK1745, 2SK1757..
2SK2645-01MR	MOS-N-FET-e	V-MOS, 600V, 9A, 50W, <1,2Ω(4,5A)	17c	Fjd	-
2SK2646-01(MR)	MOS-N-FET-e	V-MOS, 800V, 4A, 80W, <4Ω(5A)	17c$	Fjd	2SK1501, 2SK1639, 2SK1643, 2SK1807..
2SK2647-01MR	MOS-N-FET-e	=2SK2646: 40W	17c	Fjd	2SK1808, 2SK1985, 2SK2100..01, 2SK2671
2SK2648-01	MOS-N-FET-e	V-MOS, 800V, 9A, 150W, <1,5Ω(4,5A)	18c$	Fjd	2SK1796, 2SK1933, 2SK2477, 2SK2488
2SK2649-01R	MOS-N-FET-e	=2SK2648: Iso, 100W	18c	Fjd	2SK1686, 2SK2677
2SK2651-01MR	MOS-N-FET-e	V-MOS, 900V, 6A, 50W, <2,5Ω(5A)	17c	Fujitsu	-
2SK2652-01	MOS-N-FET-e	=2SK2651: 125W	18c$	Fjd	2SK1502, 2SK1614, 2SK1692, 2SK1795..
2SK2653-01R	MOS-N-FET-e	=2SK2651: 80W	18c	Fjd	2SK1365, 2SK1464, 2SK1685, 2SK1775..
2SK2654-01	MOS-N-FET-e	V-MOS, 900V, 8A, 150W, <2Ω(5A)	18c$	Fjd	2SK1502, 2SK1614, 2SK1692, 2SK1795..
2SK2655-01R	MOS-N-FET-e	=2SK2654: Iso, 100W	18c	Fjd	2SK1365, 2SK1464, 2SK1685, 2SK1775..
2SK2659	MOS-N-FET-e	V-MOS, LogL, 60V, ±15A, 45W, <70mΩ(10A)	78c	Mat	(2SK1094, 2SK1286, 2SK1419, 2SK1896,..)
2SK266	N-FET	AF-Pre, 15V, Zin>200Me	-	Tos	-
2SK2660	MOS-N-FET-e	V-MOS, 200V, ±4A, 10W, <1,1Ω(5A)	30c$	Mat	2SK1920, 2SK2099
2SK2661	MOS-N-FET-e*	V-MOS, 500V, 5A, 75W, <1,5Ω(2,5A)	17c$	Tos	BUZ41A..42, IRF830, 2SK1751, 2SK2356..
2SK2662	MOS-N-FET-e*	=2SK2661: Iso, 35W	17c	Tos	BUK445-500, 2SK1993, 2SK2115, 2SK2354..
2SK2663	MOS-N-FET-e	V-MOS, 900V, 1A, 10W, <14Ω, 17/65nS	30c$	Shi	2SK1533, 2SK3301
2SK2664	MOS-N-FET-e	V-MOS, 900V, 3A, 50W, <4,7Ω(1,5A)	17c$	Shi	2SK1456, 2SK1601, 2SK1638, 2SK1793..
2SK2665	MOS-N-FET-e	=2SK2664: 50W	30c$	Shi	2SK1510, 2SK1659, 2SK1793Z, 2SK2029..
2SK2666	MOS-N-FET-e	=2SK2664: Iso, 30W	17c	Shi	2SK1356, 2SK1460, 2SK1995, 2SK2480..
2SK2667	MOS-N-FET-e	=2SK2664: 65W	16c$	Shi	2SK1339, 2SK2719
2SK2668	MOS-N-FET-e	=2SK2664: Iso, 40W	18c	Shi	2SK1683
2SK2669	MOS-N-FET-e	V-MOS, 900V, 5A, 60W, <2,8Ω(2,5A)	17c$	Shi	2SK1643, 2SK1457, 2SK1807, 2SK2484..
2SK2670	MOS-N-FET-e	=2SK2669: 50W	30c$	Shi	2SK2006
2SK2671	MOS-N-FET-e	=2SK2669: Iso, 50W	17c	Shi	2SK1985
2SK2672	MOS-N-FET-e	=2SK2669: 80W	16c$	Shi	2SK1649, 2SK1760, 2SK1794, 2SK2482..
2SK2673	MOS-N-FET-e	=2SK2669: Iso, 80W	18c	Shi	2SK1176, 2SK1463, 2SK1684, 2SK2147..
2SK2674	MOS-N-FET-e	V-MOS, 900V, 7A, 100W, <2Ω(3,5A)	16c$	Shi	2SK1358, 2SK1462, 2SK1692, 2SK1795..
2SK2675	MOS-N-FET-e	=2SK2674: Iso, 55W	18c	Shi	2SK1465, 2SK1685, 2SK1775, 2SK2847..
2SK2676	MOS-N-FET-e	V-MOS, 900V, 10A, 120W, <1,4Ω(5A)	16c$	Shi	2SK1796, 2SK1933, 2SK2488
2SK2677	MOS-N-FET-e	=2SK2676: Iso, 65W	18c	Shi	2SK1686
2SK2678(LS)	MOS-N-FET-e	V-MOS, 600V, 1,5A, 20W, <5,5Ω(0,5A)	17c	Sanyo	BUK444-600, 2SK808, 2SK2323

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2SK2679	MOS-N-FET-e*	V-MOS, 400V, 5,5A, 35W, <1,2Ω(5A)	17c	Tos	BUK445-450, 2SK1377, 2SK1445, 2SK1990..
2SK2680	MOS-N-FET-e	V-MOS, 250V, 6A, 25W, <0,8Ω(3A)	17c	Sanyo	2SK1568..69, 2SK1668, 2SK1987, 2SK2425+
2SK2680LS	MOS-N-FET-e	V-MOS, 250V, 6A, 25W, <0,8Ω(3A)	17c	Sanyo	2SK1568..69, 2SK1668, 2SK1987, 2SK2425+
2SK2681(LS)	MOS-N-FET-e	V-MOS, 250V, 10A, 30W, <0,39Ω(5A)	17c	Sanyo	2SK1036, 2SK1762, 2SK2011, 2SK2426
2SK2682(LS)	MOS-N-FET-e	V-MOS, 250V, 13A, 35W, <0,27Ω(5A)	17c	Sanyo	2SK2012, 2SK2255, 2SK2508
2SK2683	MOS-N-FET-e	V-MOS, 250V, 16A, 40W, <0,18Ω(5A)	17c	Sanyo	2SK1818
2SK2684(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 50W, <28mΩ(10A)	30c$	Hit	2SK1900, 2SK2411Z
2SK2685	GaAs-N-FET-d	UHF, 7V, Idss=35..70mA, Up<2V, 2GHz	44z	Hit	-
2SK2687-01	MOS-N-FET-e	V-MOS, LogL, 30V, ±50A, 60W, <17mΩ	17c$	Fjd	BUK556-60, BUZ100L, 2SK2049, 2SK2499
2SK2688-01L,S	MOS-N-FET-e	V-MOS, LogL, 30V, ±50A, 60W, <0,017Ω	30c$	Fjd	2SK2499-Z, 2SK2553
2SK2689-01MR	MOS-N-FET-e	V-MOS, 30V, 50A, 40W, <0,01e	17c	Fjd	2SK1653, 2SK2312, 2SK2529
2SK2690-01	MOS-N-FET-e	V-MOS, LogL, 60V, ±80A, 125W, <17mΩ	18c$	Fjd	2SK2987, 2SK3163, 2SK3307
2SK2691-01R	MOS-N-FET-e	V-MOS, LogL, 60V, ±70A, 100W, <17mΩ	18c	Fjd	-
2SK2695	MOS-N-FET-e	V-MOS, 700V, 5A, 60W, <1,85e	17c$	Fjd	BUZ81, 2SK1501, 2SK1643, 2SK1807
2SK2696-01MR	MOS-N-FET-e	V-MOS, 700V, 5A, 50W, <1,85Ω	17c	Fujitsu	2SK1808, 2SK1985
2SK2698	MOS-N-FET-e*	V-MOS, 500V, 15A, 150W, <0,4Ω(5A)	18c$	Tos	2SK899, 2SK1610, 2SK1745, 2SK1757..
2SK2699	MOS-N-FET-e*	V-MOS, 600V, 12A, 150W, <0,65Ω(5A)	18c$	Tos	BUZ334, 2SK1723, 2SK1968, 2SK2477
2SK270	N-FET	Dual, 40V, Idss>1mA, Up<2V	7-SIP/bp1	Tos	-
2SK2700	MOS-N-FET-e*	V-MOS, 900V, 3A, 40W, <4,3Ω(1,5A)	17c	Tos	2SK1356, 2SK1460, 2SK1995, 2SK2480
2SK2701	MOS-N-FET-e	V-MOS, 450V, ±7A, 35W, <1,1Ω(3,5A)	17c	Sak	2SK1352, 2SK1805, 2SK2116..17, 2SK2237..
2SK2702	MOS-N-FET-e	V-MOS, 450V, ±10A, 35W, <0,8Ω(5A)	17c	Sak	2SK2475, 2SK2714, 2SK2842, 2SK3183
2SK2703	MOS-N-FET-e	V-MOS, 450V, ±10A, 75W, <0,8Ω(5A)	18c	Sak	2SK1225, 2SK1328, 2SK1452, 2SK1831..
2SK2704	MOS-N-FET-e	V-MOS, 450V, n13A, 40W, <0,57Ω(6,5A)...	17c	Sak	2SK3184
2SK2705	MOS-N-FET-e	V-MOS, 450V, n13A, 75W, <0,57Ω(6,5A)	18c	Sak	2SK1268, 2SK1453, 2SK2571, 2SK2572..
2SK2706	MOS-N-FET-e	V-MOS, 450V, n18A, 85W, <0,3Ω(5A)	18c	Sak	2SK1406, 2SK1525, 2SK2197, 2SK2573
2SK2707	MOS-N-FET-e	V-MOS, 600V, ±4,5A, 35W, <1,85Ω(5A)	17c	Sak	2SK2044, 2SK2097, 2SK2118, 2SK2137..
2SK2708	MOS-N-FET-e	V-MOS, 600V, ±7A, 40W, <1,1Ω(3,5A)	17c	Sak	2SK2564, 2SK2645, 2SK2740
2SK2709	MOS-N-FET-e	V-MOS, 600V, n8,5A, 85W, <0,85Ω(5A)	18c	Sak	2SK2148, 2SK2327, 2SK2710
2SK271	MOS-N-FET-e	V-MOS, Pow, 140V, 8A, 120W	23a$	Tos	2SK405, 2SK631, 2SK633
2SK2710	MOS-N-FET-e	V-MOS, 600V, ±12A, 85W, <0,55Ω(5A)	18c	Sak	2SK1405, 2SK2148, 2SK2710
2SK2711	MOS-N-FET-e	V-MOS, 250V, 16A, 30W, <0,25Ω(5A)	17c	Rhm	2SK2012, 2SK2255, 2SK2508
2SK2713	MOS-N-FET-e	V-MOS, 450V, 5A, 30W, <1,4Ω(2,5A)	17c	Rhm	2SK1351, 2SK1608, 2SK2114..15, 2SK2236..
2SK2714	MOS-N-FET-e	V-MOS, 500V, 10A, 30W, <0,9Ω(5A)	17c	Rohm	2SK2475
2SK2715	MOS-N-FET-e	V-MOS, 500V, 2A, 20W, <4Ω(5A), 22/93nS	30c$	Rhm	MTD2N50
2SK2717	MOS-N-FET-e*	V-MOS, 900V, 5A, 45W, <2,5Ω(5A)	17c	Tos	2SK1808, 2SK1985, 2SK2671
2SK2718	MOS-N-FET-e*	V-MOS, 900V, 2,5A, 40W, <6,4Ω(1,5A)	17c	Tos	2SK1174, 2SK1275, 2SK1459, 2SK1994
2SK2719	MOS-N-FET-e*	V-MOS, 900V, 3A, 125W, <4,3Ω(1,5A)	18c$	Tos	2SK727, 2SK1339, 2SK2667
2SK272	MOS-N-FET-e	=2SK271: 7A, 100W	18c$	Tos	2SK405, 2SK413..414, 2SK631, 2SK633
2SK2723	MOS-N-FE1-e*	V-MOS, LogL, 60V, ±25A, 25W, <60mΩ(10A)	17c	Nec	2SK1290, 2SK1882, 2SK1897, 2SK2934
2SK2724	MOS-N-FET-e*	V-MOS, LogL, 60V, ±35A, 30W, <40mΩ(10A)	17c	Nec	2SK2120, 2SK2291, 2SK2312, 2SK2935..
2SK2725	MOS-N-FET-e*	V-MOS, 500V, 5A, 30W, <1,6Ω(5A)	17c	Hit	2SK1351, 2SK1608, 2SK1993, 2SK2115..
2SK2726	MOS-N-FET-e*	V-MOS, 500V, 7A, 30W, <0,95Ω(5A)	17c	Hit	2SK1352, 2SK1609, 2SK1805, 2SK2117..
2SK2727	MOS-N-FET-e*	V-MOS, 500V, 10A, 125W, <0,95Ω(5A)	18c$	Hit	2SK644, 2SK724, 2SK1488, 2SK1785,..
2SK2728	MOS-N-FET-e*	V-MOS, 500V, 18A, 150W, <0,45Ω(5A)	18c$	Hit	2SK1170, 2SK1411, 2SK1500, 2SK1680..
2SK2729	MOS-N-FET-e*	V-MOS, 500V, 20A, 150W, <0,29e(10A)	18c$	Hit	2SK1170, 2SK1411, 2SK1500, 2SK1680..
2SK273	GaAs-N-FET	UHF, S..X-Band, 8V, 100mA, 12GHz	52y	Mit	-
2SK2730	MOS-N-FET-e*	V-MOS, 500V, 25A, 175W, <0,24Ω(10A)	18c$	Hit	2SK1500
2SK2731	MOS-N-FET-e*	V_MOSw, LogL, 30V, 0,2A, <2,8Ω	35a	Rhm	BSS138, BSS145, BST82, 2SK1848
2SK2733	MOS-N-FET-e*	V-MOS, 900V, 1A, 60W, <9Ω(0,5A)	17c$	Tos	BUZ50, 2SK1199, 2SK1324, 2SK1338
2SK2734	MOS-N-FET-e*	V-MOS, LogL, 30V, 5A, 0,9W, <55mΩ	7c(9mm)	Hit	2SK2989, 2SK2851
2SK2735(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 20W, <28mΩ(10A)	30c$	Hit	2SK2334, 2SK2614, 2SK2782
2SK2736	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 25W, <85mΩ(10A)	17c	Hit	2SK1262
2SK2737	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 30W, <14mΩ(20A)	17c	Hit	2SK1257, 2SK1653, 2SK1952, 2SA2120
2SK2738	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 35W, <20mΩ(20A)	17c	Hit	2SK1257, 2SK1653, 2SK1952, 2SA2120
2SK2739	MOS-N-FET-e	V-MOS, 300V, 16A, 30W, <0,33Ω(5A)	17c	Rhm	-
2SK274	GaAs-N-FET	UHF, S..X-Band, 8V, 100mA, 12GHz	52y	Mit	-
2SK2740	MOS-N-FET-e	V-MOS, 600V, 7A, 30W, <1,2Ω(5A)	17c	Rhm	2SK2645
2SK2741	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, <0,3Ω(1,5A)	39b	Tos	-
2SK2742	MOS-N-FET-e*	V-MOS, LogL, 100V, 3A, <0,45Ω(5A)	39b	Tos	-
2SK2744	MOS-N-FET-e*	V-MOS, 50V, 45A, 125W, <20mΩ(20A)	18c$	Tos	BUZ347, 2SK1998, 2SK2096, 2SK2233..
2SK2745	MOS-N-FET-e*	V-MOS, LogL, 50V, 50A, 150W, <16mΩ(20A)	18c$	Tos	2SK2121, 2SK2313, 2SK2515, 2SK2955
2SK2746	MOS-N-FET-e*	V-MOS, 800V, 7A, 150W, <1,7Ω(3,5A)	18c$	Tos	2SK1796, 2SK1933, 2SK2078, 2SK2477..
2SK2747	MOS-N-FET-e	V-MOS, LogL, 30V, 0,5A, <0,55Ω	35	Sanyo	-
2SK2748	MOS-N-FET-e	V-MOS, LogL, 30V, 2A, <0,2Ω(5A)	39b	Sanyo	2SK1311, 2SK1470, 2SK1717, 2SK2315..

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2SK2749	MOS-N-FET-e*	V-MOS, 900V, 7A, 150W, <2Ω(3,5A)	18c$	Tos	2SK1342, 2SK1502, 2SK1795, 2SK2611..
2SK275	GaAs-N-FET	UHF, S..X-Band, 8V, 100mA, 4GHz	52y	Mit	-
2SK2750	MOS-N-FET-e*	V-MOS, 600V, 3,5A, 35W, <2,2Ω(1,5A)	17c	Tos	2SK1767, 2SK2044, 2SK2118, 2SK2144
2SK2751	N-FET	AF, 40V, Idss=1,4..4,7mA, Up<3,5V	35f	Mat	-
2SK2751:	N-FET	-	35	Mat	→2SK2751
2SK2752	GaAs-N-FET	VHF/UHF, 6V, 8mA, Up=0,2..2V	44(SD-G)	Hit	-
2SK2753-01	MOS-N-FET-e	V-MOS, 120V, ±50A, 150W, <32mΩ(20A)	18c$	Fjd	-
2SK2754-01L,S	MOS-N-FET-e	V-MOS, 450V, 10A, 80W, <0,65Ω(5A)	30c$	Fjd	2SK1865, 2SK2187, 2SK2191, 2SK2366Z
2SK2755-01	MOS-N-FET-e	V-MOS, 450V, 18A, 125W, <0,45Ω(5A)	18c$	Fjd	2SK1497, 2SK1517, 2SK2057, 2SK2196..
2SK2756-01R	MOS-N-FET-e	=2SK2755: Iso, 80W	18c	Fjd	2SK1406, 2SK1525, 2SK2197, 2SK2573
2SK2757-01	MOS-N-FET-e	V-MOS, 500V, 10A, 80W, <0,9e(5A)	17c$	Fjd	2SK1503, 2SK2186, 2SK2366
2SK2758-01L,S	MOS-N-FET-e	=2SK2757:	30c$	Fjd	2SK1865, 2SK2187, 2SK2191, 2SK2366Z
2SK2759-01R	MOS-N-FET-e	V-MOS, 500V, 15A, 80W, <0,55Ω(7,2A)	18c	Mat	2SK1331, 2SK1405, 2SK1524, 2SK2195..
2SK276	GaAs N-FET	UHF, S..X-Band, 6V, 80mA, 18GHz	52y	Mit	-
2SK2760-01R	MOS-N-FET-e	V-MOS, 600V, 9A, 60W, <1,2Ω(5A)	18c	Fjd	2SK1405, 2SK1686, 2SK2148
2SK2761-01MR	MOS-N-FET-e	V-MOS, 600V, 10A, 50W, <1Ω(4,5A)	17c	Fjd	2SK2843, 2SK2996
2SK2762-01L,S	MOS-N-FET-e	V-MOS, 800V, 4A, 80W, <4Ω(5A)	30c$	Fjd	2SK1501-Z, 2SK1528, 2SK2089, 2SK2884
2SK2763-01	MOS-N-FET-e	=2SK2762: 100W	18c$	Fjd	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK2764-01R	MOS-N-FET-e	=2SK2762: Iso	18c	Fjd	2SK1463, 2SK1684, 2SK1859, 2SK2147..
2SK2765-01	MOS-N-FET-e	V-MOS, 800V, 7A, 125W, <2Ω(3,5A)	18c$	Fjd	2SK1032, 2SK1342, 2SK1358, 2SK1502..
2SK2766-01R	MOS-N-FET-e	=2SK2765: Iso, 80W	18c	Fjd	2SK1464, 2SK1685, 2SK1774..75
2SK2767-01	MOS-N-FET-e	V-MOS, 900V, 3,5A, 80W, <5,5Ω(5A)	17c$	Fjd	2SK1501, 2SK1639, 2SK1643, 2SK1807..
2SK2768-01L,S	MOS-N-FET-e	=2SK2767:	30c$	Fjd	2SK1528, 2SK2005, 2SK2006, 2SK2670
2SK2769-01MR	MOS-N-FET-e	=2SK2767: Iso, 40W	17c	Fjd	2SK1356, 2SK1460, 2SK1995, 2SK2700
2SK277	MOS-N-FET-e	V-MOS, Pow, 350V, 7A, 100W, <1,5Ω, 40/60nS	23a$	Nec	BUZ330..331, 2SK298, 2SK501
2SK2770-01	MOS-N-FET-e	=2SK2767: 100W	18c$	Fjd	2SK1339, 2SK1341, 2SK1760, 2SK1794..
2SK2771-01R	MOS-N-FET-e	V-MOS, 900V, 9A, 125W, <1,4Ω	18c	Fjd	2SK1464, 2SK1775
2SK2772	MOS-N-FET-e	V-MOS, 235V, ±4A, 10W, <1,3Ω(5A)	30c$	Mat	2SK1920, 2SK2099
2SK2773	MOS-N-FET-e	V-MOS, LogL, 30V, 20A, 35W, <37mΩ(5A)	-	Sanyo	-
2SK2775	MOS-N-FET-e	V-MOS, LogL, 100V, 25A, 40W, <110mΩ(10A)	-	Sanyo	-
2SK2776	MOS-N-FET-e*	V-MOS, 500V, 8A, 65W, <0,85Ω(5A)	30c$	Tos	2SK1316, 2SK2187, 2SK1864..65
2SK2777	MOS-N-FET-e*	V-MOS, 600V, 6A, 65W, <1,25Ω(5A)	30c$	Tos	2SK1625, 2SK1915, 2SK2089, 2SK2140Z
2SK2778	MOS-N-FET-e	V-MOS, LogL, 100V, ±12A, 30W, <0,22Ω	17c	Sak	BUK545-100, 2SK1288, 2SK1306, 2SK1558..
2SK2779	MOS-N-FET-e	V-MOS, LogL, 100V, ±20A, 35W, <95mΩ	17c	Sak	2SK1349, 2SK1906, 2SK2391, 2SK2461..
2SK278	MOS-N-FET-e	=2SK277: 400V	23a$	Nec	BUZ330..331, 2SK298, 2SK501
2SK2782	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 40W, <90mΩ(5A)	30c$	Tos	MTD20N06HDL, 2SK2334, 2SK2869, 2SK3024
2SK2787(LS)	MOS-N-FET-e	V-MOS, 450V, 8A, 40W, <0,75Ω(5A)	17c	Sanyo	2SK1352, 2SK1805, 2SK2116..17, 2SK2237..
2SK2788	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,16Ω(5A)	39b	Hit	2SK1273, 2SK1470, 2SK1717, 2SK2315..
2SK2789	MOS-N-FET-e*	V-MOS, LogL, 100V, 27A, 60W, <130mΩ(10A)	30c$	Tos	2SK3084
2SK279	GaAs-N-FET	UHF, S..X-Band, 5V, 250mA, 8GHz	52y	Mit	-
2SK2790	MOS-N-FET-e	V-MOS, 250V, ±5A, 40W, <0,7Ω(5A)	30c$	Mat	2SK1308, 2SK1691
2SK2791	MOS-N-FET-e*	V-MOS, LogL, 60V, 4A, 20W, <195mΩ(5A)	30c$	Sanyo	2SK1112, 2SK1719, 2SK1949, 2SK2231..
2SK2792	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,4Ω(5A)	17c	Rhm	2SK1118, 2SK1404, 2SK1637, 2SK2044..
2SK2793	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,5Ω(2,5A)	17c	Rohm	2SK1351, 2SK1608, 2SK1627, 2SK2236..
2SK2794	MOS-N-FET-e	V-MOS, 10V, 0,7A, Pq>31dBm(836,5MHz)	39b	Hit	-
2SK2795	MOS-N-FET-e*	V-MOS, 10V, 0,17A, Pq>24dBm(836,5MHz)	39b	Hit	-
2SK2796(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 20W, <0,16Ω(5A)	30c$	Hit	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK2797	MOS-N-FET-e	V-MOS, 200V, ±2A, 10W, <3,5Ω(5A)	30c$	Mat	2SK2235, 2SK2250
2SK2798	MOS-N-FET-e	V-MOS, 350V, 6A, 30W, <0,83Ω(5A)	17c	Shi	2SK1377, 2SK1642
2SK2799	MOS-N-FET-e	V-MOS, 350V, 10A, 50W, <0,4Ω(5A)	17c	Shi	2SK247S
2SK280	GaAs-N-FET	UHF, X..Ku-Band, 5V, 100mA, 15GHz	52y	Nec	-
2SK2800	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 40A, 50W, <20mΩ(20A)	17c$	Hit	2SK1418, 2SK1542, 2SK1911
2SK2801	MOS-N-FET-e	V-MOS, LogL, 60V, 50A, 100W, <10mΩ(20A)	17c$	Hit	BUK556-60
2SK2802	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,5A, <0,28Ω, integr. Rgate	35a	Hit	-
2SK2803	MOS-N-FET-e	V-MOS, 450V, ±3A, 30W, <2,8Ω(1,5A)	17c	Sak	BUK445-450, 2SK1444, 2SK1862..63
2SK2804	MOS-N-FET-e	V-MOS, 450V, ±5A, 35W, <1,5Ω(2,5A)	17c	Sak	2SK1351, 2SK1608, 2SK2114..15, 2SK2236..
2SK2805	MOS-N-FET-e	V-MOS, 450V, ±1SA, 80W, <0,38Ω(7,2A)	18c	Sak	2SK1268..69, 2SK1453, 2SK1524..25..
2SK2806-01	MOS-N-FET-e	V-MOS, LogL, 30V, ±35A, 30W, <0,03Ω	17c$	Fjd	BUK555-50, 2SK1542, 2SK1911, 2SK2513,..
2SK2807-01L,S	MOS-N-FET-e	V-MOS, LogL, 30V, ±35A, 30W, <0,03Ω	30c$	Fjd	2SK1919, 2SK2164, 2SK2266, 2SK2376
2SK2808-01MR	MOS-N-FET-e	V-MOS, LogL, 30V, ±35A, 20W, <0,03Ω	17c	Fjd	2SK1653, 2SK2120, 2SK2312, 2SK2580..
2SK2809-01(MR)	MOS-N-FET-e	V-MOS, LogL, 60V, ±50A, 50W, <17mΩ	17c	Fujitsu	2SK2498, 2SK2529, 2SK3027
2SK281	GaAs-N-FET	VHF, C-Band, 5V, 120mA, 8GHz	52y	Nec	-
2SK2816	MOS-N-FET-e	V-MOS, 30V, 5A, 10W	30c$	Shi	-
2SK2817	MOS-N-FET-e	V-MOS, 30V, 10A, 15W	30c$	Shi	-

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2SK2818	MOS-N-FET-e	V-MOS, 30V, 15A, 20W	30c$	Shi	-
2SK2819	MOS-N-FET-e	V-MOS, 30V, 20A, 25W	30c$	Shi	-
2SK2820	MOS-N-FET-e	V-MOS, 30V, 45A, 55W	-	Shi	-
2SK2821	MOS-N-FET-e	V-MOS, 30V, 70A, 70W	-	Shi	-
2SK2823	MOS-N-FET-e	V-MOS, LogL, 20V, 0,1A, <40Ω(10mA)	35a	Tos	BST82, 2SK1590, 2SK2158
2SK2824	MOS-N-FET-e	=2SK2823:	35a(2mm)	Tos	-
2SK2825	MOS-N-FET-e	=2SK2823:	35a(1,6mm)	Tos	-
2SK2826	MOS-N-FET-e*	V-MOS, LogL, 60V, 70A, 100W, <9,7mΩ	17c$	Nec	SPP70N10L, 2SK3096
2SK2826-S,-ZJ	MOS-N-FET-e*	=2SK2826:	30c$	-	SPB70N10L, 2SK3135
2SK2827-01	MOS-N-FET-e	V-MOS, 600V, ±9A, 60W, <1,2Ω(4,5A)	17c$	Fjd	BUK657-600, BUZ91, BUZ305
2SK2828	MOS-N-FET-e*	V-MOS, 700V, 12A, 175W, <1,2Ω(5A)	18c$	Hit	-
2SK2829	MOS-N-FET-e	V-MOS, 500V, 15A, <0,55e	18c$	Hit	2SK1610, 2SK1678, 2SK1745, 2SK1757..
2SK283	N-FET	AF-Driver, 80V, Idss>1,2mA, Up=0,75V	35f	Sanyo	-
2SK2830	MOS-N-FET-e	V-MOS, 500V, 9A, <0,55Ω	17c	Hitachi	2SK2364
2SK2832-01	MOS-N-FET-e	V-MOS, LogL, 60V, ±50A, 80W, <34mΩ(20A)	17c$	Fjd	BUK556-60, 2SK2049, 2SK2499
2SK2833-R	MOS-N-FET-e	V-MOS, LogL, 120V, ±50A, 100W, <45mΩ	18c	Fjd	-
2SK2834-01	MOS-N-FET-e	V-MOS, 600V, ±9A, 80W, <1,2Ω(4,5A)	18c$	Fjd	BUZ334, 2SK1723, 2SK1968, 2SK2477
2SK2835	MOS-N-FET-e*	V-MOS, 200V, 5A, 1,3W, <0,8Ω(2,5A)	9c	Tos	(MTD6N20E)
2SK2836	MOS-N-FET-e*	V-MOS, 600V, 1A, <9Ω(0,5A)	39b	Tos	-
2SK2837	MOS-N-FET-e*	V-MOS, 500V, 20A, 150W, <0,27Ω(10A)	18c$	Tos	2SK1411, 2SK1500, 2SK1680, 2SK2057..
2SK2838	MOS-N-FET-e*	V-MOS, Sw, Pow, 400V, 5,5A, 40W, <1,2Ω(5A)	30c$	Tos	2SK1308, 2SK1691, 2SK1750Z, 2SK2356Z..
2SK2839	MOS-N-FET-e*	V-MOS, LogL, 30V, 10A, <0,06Ω(5A)	39b	Tos	-
2SK283-R3	N-FET	-	35	Sanyo	→2SK283
2SK283-R4	N-FET	-	35	Sanyo	→2SK283
2SK283-R5	N-FET	-	35	Sanyo	→2SK283
2SK283-R6	N-FET	-	35	Sanyo	→2SK283
2SK2841	MOS-N-FET-e*	V-MOS, 400V, 10A, 80W, <0,55Ω(5A)	17c$	Tos	BUZ61, 2SK1378, 2SK1442, 2SK2365
2SK2842	MOS-N-FET-e*	V-MOS, 500V, 12A, 40W, <0,52Ω(5A)	17c	Tos	2SK2475
2SK2843	MOS-N-FET-e*	V-MOS, 600V, 10A, 45W, <0,75Ω(5A)	17c	Tos	2SK2645
2SK2844	MOS-N-FET-e*	V-MOS, LogL, 30V, 35A, 60W, <35mΩ(10A)	17c$	Tos	BUZ102AL, 2SK1911, 2SK2513, 2SK2931
2SK2845	MOS-N-FET-e*	V-MOS, 900V, 1A, 40W, <9Ω(0,5A)	30c$	Tos	-
2SK2846	MOS-N-FET-e*	V-MOS, 600V, 2A, <5Ω(5A)	12c	Tos	(IRFRC20, 2SK2040, 2SK2865)
2SK2847	MOS-N-FET-e*	V-MOS, 900V, 8A, 85W, <1,4Ω(5A)	16c	Tos	2SK1464, 2SK1775, 2SK1685..86
2SK2848	MOS-N-FET-e	V-MOS, 600V, ±2A, 30W, <3,8Ω(5A)	17c	Sak	BUK445-600, 2SK1758, 2SK1953, 2SK2043
2SK2849-01L,S	MOS-N-FET-e	V-MOS, 200V, 18A, 50W, <0,18Ω(5A)	30c$	Fjd	2SK2107, 2SK2136-Z
2SK2850-01	MOS-N-FET-e	V-MOS, 900V, ±6A, 150W, <2,5Ω(5A)	18c$	Fjd	2SK1341, 2SK1649, 2SK1760, 2SK1795..
2SK2851	MOS-N-FET-e*	V-MOS, LogL, 60V, 5A, 0,9W, <0,1Ω(2,5A)	7c(9mm)	Hit	-
2SK2854	MOS-N-FET-e	V-MOS, UHF, 10V, 0,5A, Pq=23dBmW	-	Tos	-
2SK2855	MOS-N-FET-e	V-MOS, UHF, 10V, 1A, Pq=31dBmW	-	Tos	-
2SK2856	GaAs-N-FET	V-MOS, UHF, 3V, 80mA, 1,5GHz	44(2mm)	Tos	-
2SK2857	MOS-N-FET-e*	V-MOS, LogL, 60V, ±4A, <0,22Ω	39b	Nec	2SK2741
2SK2858	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,1A, <15Ω	35a(2mm)	Nec	2SK3018
2SK2859	MOS-N-FET-e*	V-MOS, LogL, 100V, 2A, <0,55Ω(5A)	8-MDIP	Sanyo	-
2SK286	MOS-N-FET-e	V-MOS, 60V, 8A, 100W, <0,8e, 80/110nS	20d*	Hit	2SK225..227, (2SK343..344)
2SK2862	MOS-N-FET-e*	V-MOS, 500V, 3A, 25W, <3,2Ω(5A)	17c	Tos	BUK445-500, 2SK1767, 2SK2144, 2SK2750..
2SK2863	N-FET	Sw, 50V, 100mA, Idss<0,1mA	35	Mat	-
2SK2864	MOS-N-FET-e	V-MOS, 200V, 20A, 50W, <120mΩ(10A)	-	Sanyo	-
2SK2865	MOS-N-FET-e*	V-MOS, 600V, 2A, 20W, <5Ω(5A)	30c$	Tos	IRFRC20, 2SK2040
2SK2866	MOS-N-FET-e*	V-MOS, 600V, 10A, 125W, <0,75Ω(5A)	17c$	Tos	IRFB9N60A
2SK2867	MOS-N-FET-e*	V-MOS, LogL, 450V, 30mA, <0,25Ω	35	Sanyo	2SK2158
2SK2869(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 20A, 30W, <70mΩ(10A)	30c$	Hit	MTD20N06HDL, 2SK2334, 2SK2782
2SK287	MOS-N-FET-e	V-MOS, 60V, 8A, 100W, <0,6e, 25/350nS	20d*	Hit	2SK225..227, (2SK343..344)
2SK2870-01L,S	MOS-N-FET-e	V-MOS, 450V, ±8A, 50W, <1,2Ω(5A)	30c$	Fjd	2SK1315..16, 2SK1495..96Z, 2SK2359..60Z
2SK2871-01	MOS-N-FET-e	=2SK2870:	17c$	Fjd	2SK1495..96, 2SK2359..60, 2SK2408..
2SK2872-01MR	MOS-N-FET-e	=2SK2870: 30W	17c	Fjd	2SK1566..67, 2SK2116..17, 2SK2363..64,..
2SK2873-01	MOS-N-FET-e	=2SK2870: 60W	18c$	Fjd	BUZ330..31, 2SK1785, 2SK2362, 2SK2601..
2SK2874-01L,S	MOS-N-FET-e	V-MOS, 500V, ±6A, 50W, <1,5Ω(5A)	30c$	Fjd	2SK1316, 2SK1496Z, 2SK1864, 2SK2360Z..
2SK2875-01	MOS-N-FET-e	=2SK2874:	17c$	Fjd	2SK1496, 2SK1574, 2SK2360, 2SK2408..
2SK2876-01(MR)	MOS-N-FET-e	=2SK2874: 30W	17c	Fjd	2SK1567, 2SK2117, 2SK2237, 2SK2364..
2SK2877-01	MOS-N-FET-e	=2SK2870: 60W	18c$	Fjd	BUZ330..31, 2SK1785, 2SK2362, 2SK2601..
2SK2879-01	MOS-N-FET-e	V-MOS, 500V, ±20A, 150W, <0,38Ω(10A)	18c$	Fjd	2SK1411, 2SK1500, 2SK1680, 2SK2057..
2SK288	MOS-N-FET-e	=2SK287: 80V	20d*	Hit	2SK225..227, (2SK343..344)
2SK2880	N-FET	Analog-Sw, 50V, Idss=0,3..12mA, Up<6V	41	Mit	2SK381
2SK2881	N-FET	GenP, 50V, Idss=1..12mA, Up<3V	41	Mit	BF410B, BFW12, 2N4340, 2N5484..

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2SK2882	MOS-N-FET-e*	V-MOS, LogL, 150V, 18A, 45W, <0,18Ω(5A)	17c	Tos	2SK1266, 2SK2098, 2SK2377, 2SK2923
2SK2883	MOS-N-FET-e*	V-MOS, 800V, 3A, 75W, <3,6Ω(1,5A)	30c$	Tos	2SK1510, 2SK1659, 2SK1846, 2SK1858..
2SK2884	MOS-N-FET-e*	V-MOS, 800V, 5A, 100W, <2,2Ω(5A)	30c$	Tos	2SK1501Z, 2SK1528, 2SK2004, 2SK2089
2SK2885(L,S)	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 75W, <25mΩ(20A)	30c$	Hit	2SK1919, 2SK2164, 2SK2266, 2SK2376..
2SK2886	MOS-N-FET-e*	V-MOS, LogL, 50V, 45A, 40W, <36mΩ(20A)	17c	Tos	2SK1653, 2SK2120, 2SK2498, 2SK2512..
2SK2887	MOS-N-FET-e	V-MOS, 200V, 3A, 20W, <0,9Ω(1,5A)	30c$	Rhm	2SK1335
2SK2889	MOS-N-FET-e*	V-MOS, 600V, 10A, 100W, <0,75Ω(5A)	30c$	Tos	-
2SK289	MOS-N-FET-e	V-MOS, 80V, 8A, 100W, 25/350nS	23e*	Hit	2SK175..176, (BUZ33)
2SK2890-01MR	MOS-N-FET-e	V-MOS, LogL, 30V, ±50A, 50W, <10,5mΩ	17c	Fjd	2SK2498, 2SK2529, 2SK3027
2SK2891-01	MOS-N-FET-e	V-MOS, LogL, 30V, ±100A, 125W, <9,5mΩ	18c$	Fjd	IRFP064N
2SK2892-01R	MOS-N-FET-e	=2SK2891..: Iso, n90A, 100W	18c	Fjd	-
2SK2893-01	MOS-N-FET-e	V-MOS, LogL, 30V, ±100A, 150W, <7mΩ	18c$	Fjd	IRLP2505
2SK2894-01(R)	MOS-N-FET-e	=2SK2893..: Iso, 125W	18c	Fjd	2SK3028
2SK2895-01	MOS-N-FET-e	V-MOS, LogL, 60V, ±45A, 60W, <20mΩ	17c$	Fjd	BUK556-60, MTP52N06VL, 2SK1542, 2SK2049
2SK2896-01(L,S)	MOS-N-FET-e	=2SK2895..:	30c$	Fjd	MTB52N06VL, 2SK2499-Z, 2SK2553
2SK2897-01MR	MOS-N-FET-e	=2SK2895..: Iso, 40W	17c	Fjd	2SK2498, 2SK2529, 2SK2580, 2SK3027..
2SK2898-01	MOS-N-FET-e	V-MOS, LogL, 60V, ±100A, 150W, <11mΩ	18c$	Fjd	-
2SK2899-01R	MOS-N-FET-e	=2SK2898..: Iso, 125W	18c	Fjd	-
2SK290	MOS-N-FET-e	=2SK289: 100V	23e*	Hit	2SK175..176, (BUZ33)
2SK2900-01	MOS-N-FET-e	V-MOS, 60V, ±45A, 60W, <14,5mΩ(22,(A)	17c$	Fjd	BUK556-60, MTP52N06V, 2SK1542, 2SK2049
2SK2901-01(L,S)	MOS-N-FET-e	=2SK2900..:	30c$	Fjd	MTB52N06V, 2SK2499-Z, 2SK2553
2SK2902-01MR	MOS-N-FET-e	=2SK2900..: Iso, 40W	17c	Fjd	2SK2498, 2SK2529
2SK2903-01MR	MOS-N-FET-e	V-MOS, 60V, ±50A, 50W, <12mΩ(45A)	17c	Fjd	2SK2498, 2SK2529
2SK2904-01	MOS-N-FET-e	V-MOS, 60V, ±80A, 125W, <12mΩ(45A)	18c$	Fjd	2SK1423
2SK2905-01R	MOS-N-FET-e	=2SK2903..: Iso, ±70A, 100W	18c	Fjd	-
2SK2906-01	MOS-N-FET-e	V-MOS, 60V, ±100A, 150W, <7,8mΩ(50A)	18c$	Fjd	-
2SK2907-01(R)	MOS-N-FET-e	=2SK2906..: Iso, 125W	18c	Fjd	2SK3028
2SK2908-01L,S	MOS-N-FET-e	V-MOS, 600V, ±9A, 60W, <1,2Ω(4,5A)	30c$	Fjd	2SK2889
2SK2909	MOS-N-FET-e*	V-MOS, LogL, 20V, 0,8A, <0,3Ω(0,5A)	35a	Sanyo	BSH102, BSH103, 2SK2910
2SK291	N-FET	Video-Camera, 15V, Idss>5mA, Up<3V	7d	Hit	-
2SK2910	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,8A, <0,3Ω(0,5A)	35a	Sanyo	BSH102, BSH103, 3SK3000
2SK2911	MOS-N-FET-e	V-MOS, LogL, 100V, 0,25A, <3,5Ω(0,1(A)	35	Sanyo	2SK1849
2SK2912(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 40A, 50W, <40mΩ(20A)	30c$	Hit	2SK1919, 2SK2164, 2SK2266, 2SK2376..
2SK2914	MOS-N-FET-e*	V-MOS, 250V, 7,5A, 20W, <0,5Ω(3,5A)	17c$	Tos	2SK741, 2SK1319..20, 2SK1400, 2SK1667
2SK2915	MOS-N-FET-e*	V-MOS, 600V, 16A, 150W, <0,4Ω(5A)	18c$	Tos	IRFPC60, 2SK1573, 2SK2061
2SK2916	MOS-N-FET-e*	V-MOS, 500V, 14A, 80W, <0,4Ω(5A)	16c	Tos	2SK1269, 2SK1331, 2SK1524, 2SK2572
2SK2917	MOS-N-FET-e*	V-MOS, 500V, 18A, 90W, <0,27Ω(10A)	16c	Tos	2SK1406, 2SK1525, 2SK2573, 2SK2197
2SK2918-01	MOS-N-FET-e	V-MOS, 200V, ±20A, 80W, <0,13Ω(10A)	17c$	Fjd	BUZ30A, IRF650A, 2SK2136
2SK2919	MOS-N-FET-e	V-MOS, 600V, 2A, 35W, <4,3Ω(5A)	-	Sanyo	-
2SK292	N-FET	FM-V/M/0, 20V, Idss>0,5mA, Up<2,5V	40f	Nec	BF410A, 2SK193, 2SK195, 2SK212
2SK2920	MOS-N-FET-e*	V-MOS, 200V, 5A, 20W, <0,8Ω(2,5A)	30c$	Tos	MTD6N20E, 2SK1920, 2SK2099, 2SK2660
2SK2922	MOS-N-FET-e*	V-MOS, 10V, 0,7A, Pq>31dBm(836,5MHz)	39f	Hit	-
2SK2923	MOS-N-FET-e	V-MOS, LogL, 150V, ±20A, 50W, <0,1Ω	17c	Mat	2SK1266..67
2SK2924	MOS-N-FET-e	V-MOS, 350V, ±10A, 50W, <0,4(5A)	17c	Mat	2SK2702, 2SK2960
2SK2925(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 20W, <0,16Ω(5A)	30c$	Hit	IRLR024, MTD12N06EZL, 2SK2018, 2SK2414
2SK2926(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 25W, <0,11Ω(5A)	30c$	Hit	IRLR024, MTD15N06VL
2SK2927	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <0,15Ω(5A)	17c$	Hit	MTP3055VL, 2SK1114
2SK2928	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 40W, <105mΩ(5A)	17c$	Hit	BUK552-60, MTP15N06VL, 2SK2175
2SK2929	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <70mΩ(10A)	17c$	Hit	BUK555-60, 2SK1115, 2SK1287, 2SK1910
2SK293(A)	MOS-N-FET-e	V-MOS, Sw, Pow, 300V, 7A, 100W, <1,3Ω	23a*	Nec	2SK277..278, 2SK298, 2SK501
2SK2930	MOS-N-FET-e*	V-MOS, LogL, 60V, 35A, 50W, <50mΩ(10A)	17c$	Hit	MTP35N06ZL, 2SK1291, 2SK1296, 2SK2411
2SK2931	MOS-N-FET-e*	V-MOS, LogL, 60V, 45A, 75W, <25mΩ(20A)	17c$	Hit	BUK556-60, 2SK1542, 2SK1911, 2SK2513
2SK2932	MOS-N-FET-e*	=2SK2927: Iso, 20W	17c	Hit	IRLS530A, 2SK1895, 2SK1904, 2SK2579
2SK2933	MOS-N-FET-e*	=2SK2928: Iso, 25W	17c	Hit	IRLSZ24A, 2SK1286, 2SK1896, 2SK2285
2SK2934	MOS-N-FET-e*	=2SK2929: Iso, 25W	17c	Hit	2SK1882, 2SK1897, 2SK2232, 2SK2346..
2SK2935	MOS-N-FET-e*	=2SK2930: Iso, 30W	17c	Hit	2SK2120, 2SK2312, 2SK2498, 2SK2512..
2SK2936	MOS-N-FET-e*	=2SK2931: Iso, 35W	17c	Hit	2SK2120, 2SK2312, 2SK2498, 2SK2512..
2SK2937	MOS-N-FET-e*	=2SK2929: Iso, 25W	17c	Hit	2SK1095, 2SK1307, 2SK1318, 2SK1951
2SK2938(L,S)	MOS-N-FET-e*	=2SK2929:	30c$	Hit	2SK1622, 2SK1918, 2SK1967, 2SK2311..
2SK2939(L,S)	MOS-N-FET-e*	=2SK2930:	30c$	Hit	MTB35N06ZL, 2SK1900, 2SK2288Z, 2SK2411Z
2SK294	MOS-N-FET-e	V-MOS, 80V, 5A, 30W, 0,4e, 40/70nS	17c$	Hit	IRF510..513, 2SK357..358, 2SK917,..
2SK2940(L,S)	MOS-N-FET-e*	=2SK2931:	30c$	Hit	2SK1919, 2SK2164, 2SK2266, 2SK2376..
2SK2941	MOS-N-FET-e*	V-MOS, LogL, 30V, ±35A, 60W, <33mΩ(10A)	17c$	Nec	BUK555-50, 2SK1291, 2SK1296, 2SK2411,..
2SK2949	MOS-N-FET-e*	V-MOS, 400V, 10A, 80W, <0,55Ω(5A)	30c$	Tos	MTB10N40E, 2SK1865, 2SK2187, 2SK2366Z

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2SK295	MOS-N-FET-e	=2SK294:100V	17c$	Hit	IRF510,IRF512,2SK357..358,2SK917,..
2SK2950	MOS-N-FET-e	V-MOS,400V,0,5A,<23e	30c$	Mat	-
2SK2951	MOS-N-FET-e	V-MOS,200V,1A,<3,5(0,5A)	39b	Sanyo	2SK1334,2SK2992
2SK2952	MOS-N-FET-e*	V-MOS,400V,8,5A,40W,<0,55Ω(5A)	17c$	Tos	BUK657-400,BUZ61,2SK1378,2SK2365
2SK2953	MOS-N-FET-e*	V-MOS,600V,15A,90W,<0,4Ω(5A)	16c	Tos	2SK1405
2SK2954-MR	MOS-N-FET-e	V-MOS,LogL,100V,±30A,50W,<55mΩ(10A)	17c	Fjd	2SK1262,2SK2466
2SK2955	MOS-N-FET-e*	V-MOS,LogL,60V,45A,100W,<25mΩ(20A)	18c$	Hit	BUK539-60,2SK1258,2SK1379,2SK2121,..
2SK2956	MOS-N-FET-e*	V-MOS,LogL,30V,50A,35W,<18mΩ(20A)	17c	Hit	2SK2498,2SK2529
2SK2957(L,S)	MOS-N-FET-e*	=2SK2956:75W	30c$	Hit	MTB52N06,VL,2SK2499-Z,2SK2553
2SK2958(L,S)	MOS-N-FET-e*	V-MOS,LogL,30V,75A,100W,<14mΩ(45A)	30c$	Hit	IRL2505,IRL3705N
2SK2959	MOS-N-FET-e*	V-MOS,LogL,30V,50A,75W,<18mΩ(20A)	17c$	Hit	BUK556-60,MTP52N06VL,2SK1542,2SK2499
2SK296	MOS-N-FET-e	V-MOS,300V,1A,30W,2,5<4Ω,20/70nS	17c$	Hit	IRF712
2SK2960	MOS-N-FET-e	V-MOS,400V,±10A,50W,<0,52Ω(5A)	17c	Mat	..2SK2475,2SK2702,2SK2714,2SK2842..
2SK2961	MOS-N-FET-e*	V-MOS,LogL,60V,2A,0,9W,<0,38Ω(5A)	7c(9mm)	Tos	SF2N06L
2SK2962	MOS-N-FET-e*	V-MOS,LogL,100V,1A,0,9W,<0,95Ω	7c(9mm)	Tos	2SK1736,2SK2070,2SK2085
2SK2963	MOS-N-FET-e*	-	39	Tos	→2SK2963
2SK2964	MOS-N-FET-e*	V-MOS,LogL,30V,2A,<0,25Ω(5A)	39b	Tos	2SK1311,2SK1470,2SK1717,2SK2315..
2SK2965	MOS-N-FET-e*	V-MOS,200V,11A,35W,<0,26Ω(5,5A)	17c	Tos	2SK1036,2SK1762,2SK2011,2SK2212..
2SK2967	MOS-N-FET-e*	V-MOS,DC-DC,250V,30A,150W,<68mΩ	18c$	Tos	IRFP264,2SK1492,2SK1671,2SK1675..
2SK2968	MOS-N-FET-e*	V-MOS,900V,10A,150W,<1,25Ω(5A)	18c$	Tos	2SK1796,2SK1933,2SK2488,2SK2676
2SK2969	MOS-N-FET-e*	V-MOS,LogL,30V,0,8A,<0,52Ω,20/50nS	35a	Sanyo	BSH102,BSH103,IRLML2803,2SK3000
2SK2970	MOS-N-FET-e	V-MOS,200V,10A,40W,<24mΩ(5A)	-	Sanyo	-
2SK2971	MOS-N-FET-e	V-MOS,800V,3A,<4e	18c($)	Mat	BUZ307,2SK1339,2SK2719
2SK2973	MOS-N-FET-e	V-MOS,UHF,17V,Pq=1,2W(450MHz)	39f	Mit	-
2SK2976	MOS-N-FET-e*	V-MOS,LogL,30V,15A,20W,<58mΩ(5A)	30c$	Sanyo	IRLR024,IRLR130A,MTD15N06VL,2SK3031
2SK2977	MOS-N-FET-e*	V-MOS,LogL,30V,30A,30W,<35mΩ(10A)	17c	Sanyo	IRLSZ44A,2SK2289,2SK2466,2SK2935..
2SK2978	MOS-N-FET-e*	V-MOS,LogL,20V,2,5A,<0,12Ω	39b	Hit	2SK2152,2SK2316
2SK298	MOS-N-FET-e	V-MOS,400V,8A,100W,<1,75Ω,50/120nS	23a$	Hit	BUZ54,BUZ94,2SK512,2SK724
2SK2980	MOS-N-FET-e*	V-MOS,LogL,30V,1A,<0,28Ω(0,5A)	39b	Hit	2SK1586,2SK1726,2SK2111
2SK2981(-Z)	MOS-N-FET-e*	V-MOS,LogL,30V,±20A,20W,<50mΩ	30c$	Nec	IRLR2705,SPD21N05L,2SK2614
2SK2982(-Z)	MOS-N-FET-e*	V-MOS,LogL,30V,±30A,30W,<19mΩ	30c$	Nec	IRLR2905,2SK3025
2SK2983	MOS-N-FET-e*	V-MOS,LogL,30V,±30A,50W,<27mΩ(10A)	17c$	Nec	BUK555-50,MTP30N06VL,2SK2411..
2SK2983-S,-ZJ	MOS-N-FET-e*	=2SK2983:	30c$	-	MTB30N06VL,2SK1900,2SK2288Z,2SK2411Z
2SK2984	MOS-N-FET-e*	V-MOS,LogL,30V,±40A,60W,<13mΩ(20A)	17c$	Nec	BUZ102AL,PHP44N06LT,2SK1911,2SK2513..
2SK2984-S,-ZJ	MOS-N-FET-e*	=2SK2984:	30c$	Nec	2SK1792,2SK1919,2SK2266,2SK2376..
2SK2985	MOS-N-FET-e*	V-MOS,LogL,60V,45A,45W,<10mΩ(20A)	17c	Tos	2SK1653,2SK2312,2SK2498,2SK2529
2SK2986	MOS-N-FET-e*	V-MOS,LogL,60V,55A,100W,<10mΩ(30A)	30c$	Tos	MTB52N06VL,2SK2499-Z,2SK2553
2SK2987	MOS-N-FET-e*	V-MOS,LogL,60V,70A,150W,<10mΩ	18c$	Tos	2SK3163
2SK2988	N-FET	40V,10mA,Idss<4,7mA,Up<3,5V	35f(1,6mm)	Mat	-
2SK2989	MOS-N-FET-e*	V-MOS,LogL,50V,5A,0,9W,<0,33Ω	7c(9mm)	Tos	2SK2851
2SK299	MOS-N-FET-e	=2SK298:450V	23a$	Hit	BUZ54,BUZ94,2SK512,2SK724
2SK2991	MOS-N-FET-e*	V-MOS,500V,5A,50W,<1,5Ω(2,5A)	30c$	Tos	2SK1314,2SK1703S,2SK1722,2SK1751Z..
2SK2992	MOS-N-FET-e*	V-MOS,200V,1A,<3,5Ω(0,5A),17/45nS	39b	Tos	2SK1334
2SK2993	MOS-N-FET-e*	V-MOS,250V,20A,100W,<105mΩ(10A)	30c$	Tos	-
2SK2995	MOS-N-FET-e*	V-MOS,250V,30A,90W,<68mΩ(10A)	?18c($)	Tos	2SK1492,2SK1669,2SK1671,2SK1675
2SK2996	MOS-N-FET-e*	V-MOS,600V,10A,45W,<1Ω(5A)	17c	Tos	2SK2843
2SK2998	MOS-N-FET-e*	V-MOS,500V,0,5A,0,9W,<18Ω(0,25A)	7c(9mm)	Tos	-
2SK30(A,ATM)	N-FET	AF/GenP,LN,50V,Idss>0,3mA,Up<5V	7e	Tos,Mic	BFS70,2N3821,2SK40,2SK46,2SK59..
2SK300	N-FET	VHF,15V,Idss>9,5mA,Up<2V	35f	Son	(BF513)
2SK3000	MOS-N-FET-e*	V-MOS,LogL,40V,1A,<0,5Ω(0,45A),In.Rgate	35a	Hit	-
2SK3001	GaAs-N-FET-e	UHF,6V,20mA,Idss<70mA	44(2mm)	Hit	-
2SK300-1	N-FET	-	35	Mat	→2SK300
2SK300-2	N-FET	-	35	Mat	→2SK300
2SK300-3	N-FET	-	35	Mat	→2SK300
2SK300-4	N-FET	-	35	Mat	→2SK300
2SK3005	MOS-N-FET-e	V-MOS,600V,2A,20W	30c$	Shi	IRFRC20
2SK3006	MOS-N-FET-e	V-MOS,600V,4A,50W	17c$	Shi	BUK455-600,BUZ90,2SK1809,2SK1923,..
2SK3007	MOS-N-FET-e	V-MOS,600V,4A,50W	-	Shi	-
2SK3009	MOS-N-FET-e	V-MOS,600V,8A,60W,<1,2Ω(5A)	-	Shi	-
2SK301	N-FET	GenP,LN,55V,±30mA,Idss>0,5mA,Up<5V	7a	Mat	BFS70,2N3821,2N4220,2SK104..
2SK3011	MOS-N-FET-e	V-MOS,600V,8A,80W	16c($)	Shi	BUK637-600,BUZ332(A),2SK1925
2SK3012	MOS-N-FET-e	V-MOS,600V,16A,125W,<0,6Ω(5A)	16c($)	Shi	2SK1573,2SK2915
2SK3013	MOS-N-FET-e	V-MOS,600V,16A,70W,<0,6Ω(5A)	18c	Shi	2SK1405
2SK3017	MOS-N-FET-e*	V-MOS,900V,8,5A,90W,<1,25Ω(5A)	?18c($)	Tos	2SK1796,2SK1933,2SK2488,2SK2676

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2SK3018	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,1A, <8Ω(10mA)	35a(2mm)	Rhm	-
2SK3019	MOS-N-FET-e*	-	35(1,6mm)	Rhm	→2SK3019
2SK302	MOS-N-FET-d	VHF, 20V, Idss>1,5mA, Up<2,5V	35c	Tos	-
2SK3020	MOS-N-FET-e*	V-MOS, LogL, 30V, 15A, 20W, <67mΩ(5A)	30c$	Sanyo	IRLR024, IRLR130A, MTD15N06VL
2SK3021	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 30W, <33mΩ(10A)	30c$	Sanyo	IRLR034A, IRLR2705, MTD20N06HDL
2SK3022	MOS-N-FET-e*	V-MOS, LogL, 60V, ±5A, 10W, <0,2Ω(5A)	30c$	Mat	2SK1112, 2SK1471, 2SK1719, 2SK1949..
2SK3023	MOS-N-FET-e*	V-MOS, LogL, 60V, ±10A, 10W, <0,11Ω(5A	30c$	Mat	MTD12N06EZL, 2SK2018, 2SK2414..
2SK3024	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 20W, <70mΩ(10A)	30c$	Mat	IRLR034A, MTD20N06HDL, 2SK2334, 2SK2782
2SK3025	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 20W, <55mΩ(15A	30c$	Mat	2SK3385, 2SK3386
2SK3026	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 50W, <24mΩ(20A	17c	Mat	2SK2120, 2SK2312, 2SK2498, 2SK2512..
2SK3027	MOS-N-FET-e*	V-MOS, LogL, 60V, ±50A, 60W, <17mΩ(20A)	17c	Mat	2SK2498, 2SK2529
2SK3028	MOS-N-FET-e*	V-MOS, LogL, 60V, ±100A, 100W, <10mΩ(50A)	18c	Mat	-
2SK3029	MOS-N-FET-e*	V-MOS, LogL, 100V, ±5A, 10W, <0,5Ω(5A)	30c$	Mat	2SK1474, 2SK1804, 2SK2016, 2SK2399..
2SK302-GR	N-FET	-	35	Tos	→2SK302
2SK302-O	N-FET	-	35	Tos	→2SK302
2SK302-Y	N-FET	-	35	Tos	→2SK302
2SK303	N-FET	=2SK304: SMD	35f	Sanyo	2SK160
2SK3030	MOS-N-FET-e*	V-MOS, LogL, 100V, ±8A, 10W, <0,26Ω(5A)	30c$	Mat	2SK1475, 2SK1557, 2SK1560
2SK3031	MOS-N-FET-e*	V-MOS, LogL, 100V, ±15A, 20W, <0,16Ω(5A)	30c$	Mat	IRLR130A
2SK3032	MOS-N-FET-e*	V-MOS, LogL, 100V, ±25A, 10W, <0,12Ω(10A)	30c$	Mat	-
2SK3033	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 60W, <75mΩ(20A)	17c	Mat	2SK1262, 2SK2466, 2SK2577, 2SK2954
2SK3034	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 60W, <40mΩ(20A)	17c	Mat	2SK3360, 2SK3361
2SK3035	MOS-N-FET-e*	V-MOS, LogL, 150V, ±3A, 10W, <1,3Ω(5A)	30c$	Mat	2SK1335, 2SK2015
2SK3036	MOS-N-FET-e*	V-MOS, LogL, 150V, ±6A, 20W, <0,51Ω(5A)	30c$	Mat	IRLR220A, 2SK1560
2SK3037	MOS-N-FET-e*	V-MOS, LogL, 150V, ±10A, 20W, <0,3Ω(5A)	30c$	Mat	-
2SK3038	MOS-N-FET-e	V-MOS, 150V, 15A, <0,22Ω	30c$	Mat	-
2SK3039	MOS-N-FET-e	V-MOS, 150V, 20A, <0,12Ω	17c	Mat	2SK1266, 2SK2098, 2SK2377
2SK303-V2	N-FET	-	35	Sanyo	→2SK303
2SK303-V3	N-FET	-	35	Sanyo	→2SK303
2SK303-V4	N-FET	-	35	Sanyo	→2SK303
2SK303-V5	N-FET	-	35	Sanyo	→2SK303
2SK304	N-FET	Sw, 30V, Idss>0,6mA, Up<4V	40e	Sanyo	BFS70, 2N3821, 2N4220, 2SK104, 2SK301..
2SK3040	MOS-N-FET-e	V-MOS, 150V, 2,5A, <0,75Ω	17c	Mat	2SK1264..65, 2SK2588
2SK3042	MOS-N-FET-e*	V-MOS, 250V, ±7A, 35W, <0,6Ω(5A)	17c	Mat	2SK1987, 2SK2341, 2SK2417, 2SK2425..
2SK3043	MOS-N-FET-e	V-MOS, 450V, ±5A, 35W, <1,3Ω(5A)	17c	Mat	2SK1351, 2SK1608, 2SK2114..15, 2SK2236..
2SK3044	MOS-N-FET-e	V-MOS, 450V, ±7A, 40W, <0,75Ω(5A)	17c	Mat	2SK1566, 2SK1446, 2SK2116, 2SK2363
2SK3045	MOS-N-FET-e	V-MOS, 500V, ±2,5A, 30W, <4Ω(1,5A)	17c	Mat	BUK444-500, 2SK1833, 2SK1863, 2SK1989
2SK3046	MOS-N-FET-e	V-MOS, 500V, ±7A, 40W, <1Ω(5A)	17c	Mat	2SK1805, 2SK2117, 2SK2237, 2SK2364
2SK3047	MOS-N-FET-e	V-MOS, 800V, ±2A, 30W, <7Ω(5A)	17c	Matsushita	BUK446-800, 2SK1142, 2SK1611, 2SK1834
2SK3048	MOS-N-FET-e	V-MOS, 600V, ±3A, 35W, <2,5Ω(5A)	17c	Mat	2SK1572, 2SK1767, 2SK2144, 2SK2750
2SK3049	MOS-N-FET-e	V-MOS, 600V, ±5A, 40W, <1,5e(3A)	17c	Mat	2SK1118, 2SK2045, 2SK2097, 2SK2118,
2SK3050	MOS-N-FET-e	V-MOS, 600V, 2A, 24W, 4,4e	30c$	Rhm	IRFRC20, PHD2N60E, 2SK2040, 2SK2865
2SK3051	MOS-N-FET-e*	V-MOS, 50V, 45A, 40W, <30mΩ(20A)	30c$	Tos	2SK1792, 2SK2164, 2SK2266, 2SK2376..
2SK3053	MOS-N-FET-e*	V-MOS, LogL, 60V, ±25A, 30W, <70mΩ	17c	Nec	2SK1882, 2SK1897, 2SK2232, 2SK2346..
2SK3054	MOS-N-FET-e*	V-MOS, LogL, 50V, ±0,1A, <40Ω(10mA)	35a(2mm)	Nec	2SK1590..91, 2SK2158
2SK3055	MOS-N-FET-e*	V-MOS, LogL, 60/20V, ±30A, 25W, <50mΩ	17c	Nec	2SK2120, 2SK2312, 2SK2498, 2SK2512..
2SK3056	MOS-N-FET-e*	V-MOS, LogL, 60V, ±32A, 34W, <50mΩ(10A)	17c$	Nec	BUK556-60, 2SK1542, 2SK1911, 2SK2513
2SK3056-S,-ZJ	MOS-N-FET-e*	=2SK3056:	30c$	-	MTB35N06ZL, 2SK1900, 2SK2288Z, 2SK2411Z
2SK3057	MOS-N-FET-e*	V-MOS, LogL, 60V, ±45A, 30W, <27mΩ(20A)	17c	Nec	2SK2498, 2SK2529, 2SK3027
2SK3058	MOS-N-FET-e*	V-MOS, LogL, 60V, ±55A, 58W, <27mΩ(20A)	17c$	Nec	BUK556-60, MTP52N06VL, 2SK2049
2SK3058-S,-ZJ	MOS-N-FET-e*	=2SK3058:	30c$	-	MTB52N06VL, 2SK2499Z, 2SK2553
2SK3059	MOS-N-FET-e*	V-MOS, LogL, 60V, ±50A, 30W, <23mΩ(20A)	17c	Nec	2SK2498, 2SK2529, 2SK3027
2SK3060	MOS-N-FET-e*	V-MOS, LogL, 60V, 70A, 70W, <23mΩ(35A)	17c$	Nec	IRL2505, IRL3705N, PHP125N06LT,
2SK3060-S	MOS-N-FET-e*	=2SK3060:	30c$	-	2SK3135
2SK3061	MOS-N-FET-e*	V-MOS, LogL, 60V, ±70A, 35W, <12mΩ(30A)	17c	Nec	2SK3229
2SK3062	MOS-N-FET-e*	V-MOS, LogL, 60V, ±70A, 100W, <12mΩ	17c$	Nec	2SK3069
2SK3062-S,-ZJ	MOS-N-FET-e*	=2SK3062:	30c$	-	2SK3135
2SK3064	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,1A, <50Ω(100mA)	35a(2mm)	Mat	-
2SK3065	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,32Ω(5A)	39b	Rhm	2SK1273, 2SK1470, 2SK1717, 2SK2315..
2SK3067	MOS-N-FET-e*	V-MOS, 600V, 2A, 25W, <5Ω(5A)	17c	Tos	BUK445-600, 2SK1758, 2SK1953, 2SK2324..
2SK3068	MOS-N-FET-e*	V-MOS, 500V, 12A, 100W, <0,52©(5A)	30c$	Tos	2SK1865, 2SK2191
2SK3069	MOS-N-FET-e	V-MOS, LogL, 60V, 75A, 100W, <12mΩ(45A)	17c$	Hit	-
2SK3070(L,S)	MOS-N-FET-e	V-MOS, LogL, 40V, 75A, 100W, <7,5mΩ(45A)	17c$	Hit	-
2SK3072	MOS-N-FET-e	V-MOS, LogL, 450V, 30mA, <275mΩ(15(A)	35	Sanyo	-

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2SK3074	MOS-N-FET-e	V-MOS, LogL, VHF/UHF, 30V, 1A, Gp>15dB(520MHz)	39f	Tos	-
2SK3075	MOS-N-FET-e	V-MOS, LogL, VHF/UHF, 30V, 5A, Gp>11dB(520MHz)	-	Tos	-
2SK3076(L,S)	MOS-N-FET-e*	V-MOS, 500V, 7A, 60W, <0,9e(5A)	30c$	Hit	SSW7N60A, 2SK1625, 2SK2060, 2SK2140Z
2SK308	MOS-N-FET-e	V-MOS, 120V, 10A, 100W, <0,3Ω, 60/160nS	23a$	Hit	BUZ35, 2SK401, 2SK631, 2SK633
2SK3080	MOS-N-FET-e*	V-MOS, LogL, 30V, 30A, 50W, <50mΩ(10A)	17c$	Hit	BUK555-50, 2SK1291, 2SK1296, 2SK2411
2SK3081	MOS-N-FET-e*	V-MOS, LogL, 30V, 45A, 75W, <14mΩ(20A)	17c$	Hit	BUZ102AL, 2SK1542, 2SK1911, 2SK2513
2SK3082(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <0,15Ω(5A)	30c$	Hit	2SK1907, 2SK2041, 2SK2282
2SK3083	MOS-N-FET-e	V-MOS, 150V, 3A, 1W, <2,2Ω(0,5A)	9c	Sanyo	-
2SK3084	MOS-N-FET-e*	V-MOS, LogL, 100V, 30A, 65W, <70mΩ(10A)	30c$	Tos	2SK2789
2SK3089	MOS-N-FET-e*	V-MOS, 30V, 40A, 50W, <30mΩ(20A)	30c$	Tos	PHB44N06LT, 2SK2290, 2SK2376, 2SK3051..
2SK3090	MOS-N-FET-e*	V-MOS, 30V, 45A, 60W, <20mΩ(20A)	30c$	Tos	PHB44N06LT, 2SK2290, 2SK2376, 2SK3051..
2SK3092	MOS-N-FET-e	V-MOS, 400V, 3A, 30W, <2,3Ω(1,5A)	30c$	Sanyo	IRFR320(A)
2SK3093	MOS-N-FET-e	V-MOS, 400V, 3A, 20W, <2,3Ω(1,5A)	17c	Sanyo	BUK445-450, 2SK1444, 2SK1862..63
2SK3094	MOS-N-FET-e	V-MOS, 400V, 5,5A, 55W, <1,2Ω(2,5A)	17c	Sanyo	BUK445-400, 2SK1377, 2SK2114..15..
2SK3095	MOS-N-FET-e	V-MOS, 400V, 5A, 25W, <1,2Ω(2,5A)	17c	Sanyo	BUK445-400, 2SK1377, 2SK2114..15..
2SK3096	MOS-N-FET-e	V-MOS, 400V, 7A, 70W, <0,87Ω(3,5A)	17c$	Sanyo	IRF840, IRF842, 2SK1495, 2SK2359..
2SK3097	MOS-N-FET-e	V-MOS, 400V, 6,5A, 30W, <0,87Ω(3,5A)	17c	Sanyo	IRFS750A, 2SK1642
2SK3098	MOS-N-FET-e	V-MOS, 400V, 12A, 85W, <0,55Ω(5A)	17c$	Sanyo	IRF740, IRF750A, 2SK1442, 2SK2365
2SK3099	MOS-N-FET-e	V-MOS, 400V, 9A, 30W, <0,55Ω(5A)	17c	Sanyo	2SK2702, 2SK2960, 2SK3126
2SK310	MOS-N-FET-e	V-MOS, 400V, 3A, 40W, <4e, 25/70nS	17c$	Hit	BUZ60, BUZ76, IRF720, IRF722, 2SK1244+
2SK3100	MOS-N-FET-e	V-MOS, 400V, 16A, 90W, <0,4Ω(5A)	17c$	Sanyo	IRF750A
2SK3101	MOS-N-FET-e	V-MOS, 400V, 11A, 40W, <0,4Ω(5A)	17c	Sanyo	2SK2704, 2SK3168, 2SK3184
2SK3105	MOS-N-FET-e*	V-MOS, LogL, 30V, ±2,5A, <0,15Ω	35a	Nec	-
2SK3107	MOS-N-FET-e*	V-MOS, LogL, 30V, ±0,1A, <15Ω	35a(1,6mm)	Nec	2SK1824
2SK3108	MOS-N-FET-e*	V-MOS, 200V, ±8A, 25W, <0,4Ω(5A)	17c	Nec	BUK545-200, 2SK1668, 2SK2160..61..
2SK3109	MOS-N-FET-e*	V-MOS, 200V, ±10A, 50W, <0,4Ω(5A)	17c$	Nec	BUK456-200, 2SK1393, 2SK1762, 2SK3214
2SK3109-S,-ZJ	MOS-N-FET-e*	=2SK3109:	30c$	-	2SK1636, 2SK2133-Z, 2SK2254
2SK311	MOS-N-FET-e	=2SK310: 450V	17c$	Hit	BUZ41A..42, 2SK1244, 2SK1493..1494,..
2SK3110	MOS-N-FET-e*	V-MOS, 200V, ±14A, 35W, <0,18Ω(5A)	17c	Nec	2SK1350, 2SK2012, 2SK2135, 2SK2382
2SK3111	MOS-N-FET-e*	V-MOS, 200V, ±20A, 65W, <0,18Ω(10A)	17c$	Nec	BUZ30A, IRF650A, 2SK2918
2SK3111-S,-ZJ	MOS-N-FET-e*	=2SK3111:	30c$	-	MTB20N20E, 2SK2107, 2SK2136-Z
2SK3112	MOS-N-FET-e*	V-MOS, 200V, ±25A, 70W, <0,11Ω(10A)	17c$	Nec	IRF650A
2SK3112-S,-ZJ	MOS-N-FET-e*	=2SK3112:	30c$	-	-
2SK3113(-Z)	MOS-N-FET-e*	V-MOS, 600V, ±2A, 20W, <4,4Ω(5A)	30c$	Nec	IRFRC20, 2SK2040, 2SK2865
2SK3114	MOS-N-FET-e	V-MOS, 600V, ±4A, 30W, <2,2e(2A)	17c	Nec	2SK1118, 2SK2045, 2SK2097, 2SK2118,
2SK3115	MOS-N-FET-e	V-MOS, 600V, ±6A, 35W, <1,2Ω(5A)	17c	Nec	2SK1404, 2SK1637, 2SK2044
2SK3116	MOS-N-FET-e	V-MOS, 600V, n7,5A, 70W, <1,2Ω(3,7(A)	17c$	Nec	BUK657-600, BUZ91, BUZ305
2SK3116-S,-ZJ	MOS-N-FET-e	=2SK3116:	30c$	-	SSW7N60A, 2SK2060, 2SK2889, 2SK2908..
2SK3117	MOS-N-FET-e*	V-MOS, 500V, 20A, 150W, <0,27Ω(10A)	30c$	Tos	-
2SK3119	MOS-N-FET-e*	V-MOS, LogL, 20V, 2A, <0,48Ω(0,5A)	39b	Sanyo	2SK2103, 2SK2748, 2SK2978
2SK312	MOS-N-FET-e	V-MOS, 400V, 12A, 125W, <0,9Ω, 70/200nS	23a$	Hit	BUZ45, BUZ64, 2SK512, 2SK724
2SK3120	MOS-N-FET-e*	V-MOS, LogL, 30V, 2A, <0,48Ω(0,5A)	39b	Sanyo	2SK2103, 2SK2748
2SK3121	MOS-N-FET-e*	V-MOS, LogL, 20V, 3A, <0,22Ω(0,5A)	39b	Sanyo	2SK2054
2SK3122	MOS-N-FET-e*	V-MOS, LogL, 30V, 3A, <0,32Ω(0,5A)	39b	Sanyo	2SK2054
2SK3123	MOS-N-FET-e	V-MOS, 60V, ±15A, 15W, <0,08Ω(5A)	78b	Mat	(2SK943, 2SK1345..46)
2SK3124	MOS-N-FET-e	V-MOS, 400V, ±0,5A, 10W, <0,23Ω(0,5A)	30c$	Mat	IRFR310(A), MTD1N40, 2SK945, 2SK1151
2SK3126	MOS-N-FET-e*	V-MOS, 450V, 10A, 40W, <0,65Ω(5A)	17c	Tos	2SK2475, 2SK2702, 2SK2714, 2SK2842..
2SK3127	MOS-N-FET-e*	V-MOS, 30V, 45A, 65W, <12mΩ(20A)	30c$	Tos	PHB44N06LT, 2SK2290, 2SK2376, 2SK3051..
2SK3128	MOS-N-FET-e*	V-MOS, 30V, 60A, 150W, <12mΩ(30A)	18c$	Tos	BUZ342, BUZ346, 2SK1379, 2SK2515
2SK313	MOS-N-FET-e	=2SK312: 450V	23a$	Hit	BUZ45, 2SK512, 2SK724
2SK3131	MOS-N-FET-e*	V-MOS, 500V, 50A, 250W, <0,11Ω(20A)	77c$	Tos	2SK1522, 2SK1837
2SK3132	MOS-N-FET-e*	V-MOS, 500V, 50A, 250W, <95mΩ(20A)	77c$	Tos	2SK1522, 2SK1837
2SK3133(L,S)	MOS-N-FET-e	V-MOS, LogL, 30V, 50A, 50W, <18mΩ(20A)	30c$	Hit	MTB52N06VL, 2SK2499-Z, 2SK2553
2SK3134(L,S)	MOS-N-FET-e	V-MOS, LogL, 30V, 75A, 100W, <8,5mΩ(45A)	30c$	Hit	IRL2505..IRL3705, 2SK3070
2SK3135(L,S)	MOS-N-FET-e	V-MOS, LogL, 60V, 75A, 100W, <12mΩ(30A)	30c$	Hit	-
2SK3136	MOS-N-FET-e	V-MOS, LogL, 40V, 75A, 100W, <10mΩ(45A)	17c$	Hit	IRL2505, IRL3705N, 2SK3069
2SK314	N-FET	GenP, LN, 40V, 50mA, Idss>5mA, Up<3V	2b&	Nec	BC264, BF410C, 2SK147, 2SK168
2SK3140	MOS-N-FET-e	V-MOS, LogL, 60V, 60A, 35W, <12mΩ(30A)	17c	Hitachi	2SK3229
2SK3141	MOS-N-FET-e	V-MOS, LogL, 30V, 75A, 100W, <8,5mΩ(45A)	17c$	Hit	IRL1004, IRL3705N, PHP80N06LT, 2SK3136
2SK3142	MOS-N-FET-e	V-MOS, LogL, 30V, 60A, 35W, <8,5mΩ(30A)	17c	Hit	IRLI3803, IRLI2202N
2SK3147(L,S)	MOS-N-FET-e*	V-MOS, LogL, 100V, 5A, 20W, <0,18Ω(5A)	30c$	Hit	2SK1474, 2SK1804, 2SK2016, 2SK2399..
2SK3148	MOS-N-FET-e*	V-MOS, LogL, 120V, 20A, 30W, <85mΩ(10A)	17c	Hit	IRLI540N, 2SK1266, 2SK1307, 2SK1318
2SK3149	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 50W, <85mΩ(10A)	17c$	Hit	BUK555-100, 2SK1116, 2SK1289, 2SK1347
2SK315	N-FET	FM-V/M/0,20V, Idss>2,5mA, Up<3,5V	40d	Sanyo	BF410B, 2SK192

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2SK3150(L,S)	MOS-N-FET-e*	V-MOS, LogL, 100V, 20A, 50W, <85mΩ(10A)	30c$	Hit	BUK565-100A, IRLW540A, 2SK1623, 2SK1909
2SK3151	MOS-N-FET-e*	V-MOS, LogL, 100V, 50A, 125W, <25mΩ(20A)	18c$	Hit	2SK1381
2SK3152	MOS-N-FET-e*	V-MOS, LogL, 120V, 10A, 25W, <0,17Ω(5A)	17c	Hit	IRLI640G, 2SK1035, 2SK2131, 2SK2212
2SK3153	MOS-N-FET-e*	V-MOS, LogL, 120V, 15A, 30W, <110mΩ(5A)	17c	Hit	2SK2131, 2SK2882, 2SK3155
2SK3154	MOS-N-FET-e*	V-MOS, LogL, 150V, 15A, 50W, <0,15Ω(5A)	17c$	Hit	IRL640(A), BUK555-200, 2SK1561
2SK3155	MOS-N-FET-e*	V-MOS, LogL, 150V, 15A, 30W, <0,15Ω(5A)	17c	Hit	2SK2131, 2SK2882
2SK3156	MOS-N-FET-e*	V-MOS, LogL, 150V, 20A, 75W, <80mΩ(10A)	17c$	Hit	-
2SK3157	MOS-N-FET-e*	V-MOS, LogL, 150V, 20A, 35W, <80mΩ(10A)	17c	Hit	2SK1266, 2SK2377, 2SK2933
2SK3158	MOS-N-FET-e*	V-MOS, LogL, 150V, 30A, 100W, <63mΩ(10A)	17c$	Hit	-
2SK3159	MOS-N-FET-e*	V-MOS, LogL, 150V, 50A, 125W, <48mΩ(20A)	18c$	Hit	-
2SK316	N-FET	Video-Camera, 10V, Idss>5mA, Up<3V	35f	Mat	2SK321
2SK3160	MOS-N-FET-e*	V-MOS, LogL, 200V, 10A, 30W, <0,19Ω(5A)	17c	Hit	IRLI640G, 2SK2212
2SK3161(L,S)	MOS-N-FET-e*	V-MOS, LogL, 200V, 15A, 75W, <125mΩ(5A)	30c$	Hit	BUK565-200A, IRLW640A
2SK3162	MOS-N-FET-e*	V-MOS, LogL, 200V, 20A, 35W, <85mΩ(10A)	17c	Hit	-
2SK3163	MOS-N-FET-e*	V-MOS, LogL, 60V, 75A, 110W, <12mΩ(45A)	18c$	Hit	2SK2987
2SK3166	MOS-N-FET-e*	V-MOS, 450V, ±5A, 40W, <1,4Ω(2,5A)	17c	Mat	2SK1231, 2SK1608, 2SK1626, 2SK2114..
2SK3168	MOS-N-FET-e*	V-MOS, 450V, ±15A, 60W, <0,45Ω(7,2A)	17c	Mat	2SK2704, 2SK3184
2SK316-P	N-FET	-	35	Mat	→2SK316
2SK316-Q	N-FET	-	35	Mat	→2SK316
2SK317	MOS-N-FET-e*	V-MOS, VHF-Pow, 180V, 8A, Pq>120W(100MHz)	57y	Hit	-
2SK3176	MOS-N-FET-e*	V-MOS, 200V, 30A, 150W, <52mΩ(10A)	18c$	Tos	BUZ341, IRFP250, MTW32N20E, 2SK1675
2SK3177	MOS-N-FET-e*	V-MOS, LogL, 200V, 15A, 35W, <125mΩ(5A)	17c	Hit	-
2SK3179	GaAs-N-FET-d	VHF/UHF, 4V, 80mA, Idss<80mA, Up=0,2..2V, Gp=17dB(2GHz)	44v(2mm)	Tos	-
2SK318	MOS-N-FET-e*	V-MOS, VHF-Pow, 180V, 4A, Pq>90W(100MHz)	57y	Hit	-
2SK3183	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <0,75Ω(5A)	17c	Matsushita	2SK2475, 2SK2714, 2SK2842
2SK3184	MOS-N-FET-e	V-MOS, 500V, 15A, 60W, <0,5Ω(7,2A)	17c	Matsushita	-
2SK319	MOS-N-FET-e	V-MOS, 400V, 5A, 50W, <1,83e, 50/120nS	17c$	Hit	BUZ41A..42, BUZ60, 2SK893, 2SK1246,..
2SK32	N-FET	GenP, 35V, 20mA, Idss<10mA, Up<4V	7e	Nec	BFS70, 2N3821, 2SK40, 2SK46, 2SK59..
2SK320	MOS-N-FET-e	=2SK319: 450V	17c$	Hit	BUZ41A..42, 2SK552, 2SK893, 2SK1246,..
2SK3204	MOS-N-FET-e*	V-MOS, LogL, 60V, ±15A, 1,8W, <60mΩ(5A)	78c	Nec	(2SK1094, 2SK1286, 2SK1896, 2SK2285)
2SK3205	MOS-N-FET-e*	V-MOS, LogL, 150V, 5A, 20W, <0,75Ω	30c$	Tos	IRLR220A, 2SK1560, 2SK3036
2SK3207	MOS-N-FET-e*	V-MOS, LogL, 150V, 18A, 35W, <120mΩ(5A)	17c	Hit	2SK1266, 2SK2377, 2SK2923, 2SK3157
2SK3209	MOS-N-FET-e*	V-MOS, LogL, 150V, 25A, 35W, <63mΩ(10A)	17c	Hit	-
2SK321	N-FET	Video-Camera, 15V, Idss>5mA, Up<3V	35f	Mat	-
2SK3210(L,S)	MOS-N-FET-e*	V-MOS, LogL, 150V, 30A, 100W, <63mΩ(10A)	30c$	Hit	-
2SK3211(L,S)	MOS-N-FET-e*	V-MOS, LogL, 200V, 25A, 100W, <85mΩ(10A)	30c$	Hit	-
2SK3212	MOS-N-FET-e*	V-MOS, LogL, 100V, 10A, 20W, <0,18Ω(5A)	17c	Hit	BUK545-100, IRLS530A, 2SK1305, 2SK1035
2SK3214	MOS-N-FET-e*	V-MOS, LogL, 200V, 10A, 50W, <0,19Ω	17c$	Hit	BUK555-200, IRL640A
2SK3215	MOS-N-FET-e*	V-MOS, LogL, 200V, 8A, 40W, <0,55Ω	17c$	Hit	BUK554-200, IRL630A
2SK3216-01	MOS-N-FET-e	V-MOS, 100V, ±50A, 135W, <25mΩ(20A)	17c$	Fjd	SPP70N10L
2SK3217-01MR	MOS-N-FET-e	V-MOS, 100V, ±50A, 70W, <25mΩ(20A)	17c	Fjd	-
2SK3218-01	MOS-N-FET-e	V-MOS, 150V, ±40A, 135W, <43mΩ(20A)	17c$	Fjd	-
2SK3219-01MR	MOS-N-FET-e	V-MOS, 150V, ±40A, 70W, <43mΩ(20A)	17c	Fjd	-
2SK321-P	N-FET	-	35	Mat	→2SK321
2SK321-Q	N-FET	-	35	Mat	→2SK321
2SK321-R	N-FET	-	35	Mat	→2SK321
2SK321-S	N-FET	-	35	Mat	→2SK321
2SK322	N-FET	HF, 15V, 50mA, Idss>5mA, Up<3V	35f	Hit	-
2SK3221	MOS-N-FET-e	V-MOS, 600V, ±2A, 25W, <4,4Ω(5A)	17c	Nec	BUK445-600, 2SK1834, 2SK2043, 2SK2324..
2SK3224(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 20W, <65me(10A)	30c$	Nec	IRLR034A, MTD20N06HDL, 2SK2334, 2SK2782
2SK3225(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±25A, 30W, <40mΩ(10A)	30c$	Nec	2SK3025
2SK3228	MOS-N-FET-e	V-MOS, LogL, 80V, 75A, 100W, <12mΩ	17c$	Hit	SPP70N10L
2SK3229	MOS-N-FET-e	V-MOS, LogL, 80V, 60A, 35W, <12mΩ	17c	Hitachi	-
2SK322-E	N-FET	-	35	Hit	→2SK322
2SK322-F	N-FET	-	35	Hit	→2SK322
2SK322-G	N-FET	-	35	Hit	→2SK322
2SK322-H	N-FET	-	35	Hit	→2SK322
2SK322-P	N-FET	-	35	Hit	→2SK322
2SK322-Q	N-FET	-	35	Hit	→2SK322
2SK322-R	N-FET	-	35	Hit	→2SK322
2SK322-S	N-FET	-	35	Hit	→2SK322
2SK322-T	N-FET	-	35	Hit	→2SK322
2SK323	N-FET	GenP, 40V, Idss>1,6mA, Up<1,5V	35f	Hit	-
2SK3237	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,5Ω(2,5A)	17c	Sanyo	BUK445-400, 2SK1377, 2SK2114..15..

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2SK3238	MOS-N-FET-e	V-MOS, 500V, 5A, 30W, <1,5Ω(2,5A)	30c$	Sanyo	IRFW830, 2SK1722, 2SK1751Z, 2SK2991..
2SK3239	MOS-N-FET-e	V-MOS, 500V, 5A, 40W, <1,5Ω(2,5A)	-	Sanyo	-
2SK323-B	N-FET	-	35	Hit	→2SK323
2SK323-C	N-FET	-	35	Hit	→2SK323
2SK323-D	N-FET	-	35	Hit	→2SK323
2SK323-E	N-FET	-	35	Hit	→2SK323
2SK324	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 10A, 120W, <0,6Ω	23a$	Tos	BUZ45, BUZ64, 2SK312..313
2SK3240	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,5Ω(2,5A)	17c$	Sanyo	BUK455-600, IRF830, 2SK1156, 2SK1246..
2SK3241	MOS-N-FET-e	V-MOS, 600V, 4A, 30W, <2,2Ω(5A)	17c	Sanyo	2SK2097, 2SK2118, 2SK2139, 2SK2326..
2SK3242	MOS-N-FET-e	V-MOS, 600V, 4A, 50W, <2,2Ω(5A)	30c$	Sanyo	PHB4N60E, 2SK1624, 2SK1915, 2SK2777
2SK3243	MOS-N-FET-e	V-MOS, 600V, 4A, 40W, <2,2Ω(5A)	-	Sanyo	-
2SK3244	MOS-N-FET-e	V-MOS, 600V, 4A, 50W, <2,2Ω(5A)	17c$	Sanyo	BUK455-600, 2SK1117, 2SK1809, 2SK1923..
2SK3245	MOS-N-FET-e	V-MOS, 600V, 8A, 40W, <1,2Ω(5A)	17c	Sanyo	=2SK2564, 2SK2645, 2SK2708, 2SK2740..
2SK3246	MOS-N-FET-e	V-MOS, 600V, 8A, 90W, <1,2Ω(5A)	30c$	Sanyo	PHB9N60E, 2SK1625, 2SK2060, 2SK2908..
2SK3247	MOS-N-FET-e	V-MOS, 600V, 8A, 50W, <1,2Ω(5A)	-	Sanyo	-
2SK3248	MOS-N-FET-e	V-MOS, 600V, 8A, 105W, <1,2Ω(5A)	18c$	Sanyo	BUZ332(A), IRFPC48, 2SK1925, 2SK2834
2SK3249	MOS-N-FET-e	V-MOS, 600V, 8A, 55W, <1,2Ω(5A)	18c	Sanyo	2SK2148, 2SK2327, 2SK2709, 2SK2710
2SK325	MOS-N-FET-e	=2SK324: 450V, <0,7Ω	23a$	Tos	BUZ45, BUZ339, 2SK313, 2SK724
2SK3250	MOS-N-FET-e	V-MOS, 500V, 10A, 35W, <1Ω(5A)	17c	Sanyo	2SK2475, 2SK2714, 2SK2842, 2SK3183..
2SK3251	MOS-N-FET-e	V-MOS, 500V, 10A, 60W, <1Ω(5A)	30c$	Sanyo	PHB11N50E, 2SK1865, 2SK2187, 2SK2191
2SK3252	MOS-N-FET-e	V-MOS, 500V, 10A, 45W, <1Ω(5A)	-	Sanyo	-
2SK3253	MOS-N-FET-e	V-MOS, 500V, 10A, 70W, <1Ω(5A)	18c$	Sanyo	BUZ334, 2SK1488, 2SK1516, 2SK2362..
2SK3254	MOS-N-FET-e	V-MOS, 500V, 10A, 50W, <1Ω(5A)	18c	Sanyo	2SK1523, 2SK1696, 2SK1832, 2SK2193..
2SK3255	MOS-N-FET-e	V-MOS, 900V, 5A, 35W, <2,8Ω(2,5A)	17c	Sanyo	2SK1808, 2SK1985, 2SK2671
2SK3256	MOS-N-FET-e	V-MOS, 900V, 5A, 90W, <2,8Ω(2,5A)	30c$	Sanyo	2SK1501Z, 2SK1528, 2SK2006, 2SK2670
2SK3257	MOS-N-FET-e	V-MOS, 900V, 5A, 50W, <2,8Ω(2,5A)	-	Sanyo	-
2SK3258	MOS-N-FET-e	V-MOS, 900V, 5A, 100W, <2,8Ω(2,5A)	18c$	Sanyo	2SK1760, 2SK1794, 2SK2482, 2SK2610..
2SK3259	MOS-N-FET-e	V-MOS, 900V, 5A, 55W, <2,8Ω(2,5A)	18c	Sanyo	2SK1463, 2SK1684, 2SK1859, 2SK2147..
2SK3260	MOS-N-FET-e	V-MOS, 900V, 10A, 150W, <1,4Ω(5A)	18c$	Sanyo	2SK1796, 2SK1933, 2SK2488, 2SK2676..
2SK3261	MOS-N-FET-e	V-MOS, 900V, 10A, 60W, <1,4Ω(5A)	18c	Sanyo	2SK1686, 2SK2677
2SK3262-01MR	MOS-N-FET-e	V-MOS, LogL, 200V, ±20A, 45W, <0,15Ω	17c	Fjd	2SK3162
2SK3265	MOS-N-FET-e*	V-MOS, 700V, 10A, 45W, <0,75Ω(5A)	17c	Tos	-
2SK3270-01	MOS-N-FET-e	V-MOS, 60V, ±80A, 135W, <6,5mΩ(45A)	17c$	Fjd	IRF1010E
2SK3271-01	MOS-N-FET-e	V-MOS, 60V, ±100A, 155W, <6,5mΩ(50A)	18c$	Fjd	-
2SK3272-01(L,S)	MOS-N-FET-e	V-MOS, 60V, ±80A, 135W, <6,5mΩ(45A)	30c$	Fjd	-
2SK3273-01MR	MOS-N-FET-e	V-MOS, 60V, ±70A, 70W, <6,5mΩ(30A)	17c	Fjd	-
2SK3280	MOS-N-FET-e*	V-MOS, LogL, 30V, 20A, 30W, <31mΩ(10A)	30c$	Tos	IRLR2705, SPD21N05L, 2SK2334, 2SK2782
2SK3285	MOS-N-FET-e*	V-MOS, LogL, 30V, 40A, 40W, <34mΩ(5A)	30c$	Sanyo	2SK1919, 2SK2164, 2SK2266, 2SK2376..
2SK3287	MOS-N-FET-e*	V-MOS, LogL, 30V, 0,3A, <3,44Ω	35a	Hit	BSS138, 2SK1848
2SK3289	MOS-N-FET-e*	-	35(2mm)	Hit	→2SK3289
2SK3291	MOS-N-FET-e*	V-MOS, LogL, 60V, 1,6A, <0,68Ω	39b	Sanyo	2SK1311, 2SK1470, 2SK1717, 2SK2055..
2SK3292	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, <0,44Ω	39b	Sanyo	2SK1311, 2SK1470, 2SK1717, 2SK2055..
2SK3293	MOS-N-FET-e*	V-MOS, LogL, 60V, 3A, <0,21Ω	39b	Sanyo	2SK2054, 2SK2742
2SK3294	MOS-N-FET-e*	V-MOS, 250V, ±20A, 70W, <160mΩ(10A)	17c$	Nec	IRF654A, IRF2525
2SK3294-S,-ZJ	MOS-N-FET-e*	=2SK3294:	30c$	-	2SK2063, 2SK2254
2SK3295	MOS-N-FET-e*	V-MOS, LogL, 20V, ±35A, 35W, <17mΩ(10A)	17c$	Nec	MTP35N06ZL, 2SK2513, 2SK2930
2SK3295-S,-ZJ	MOS-N-FET-e*	=2SK3295:	30c$	-	MTB35N06ZL, 2SK2513-Z, 2SK2939, 2SK3051
2SK3296	MOS-N-FET-e*	V-MOS, LogL, 20V, ±35A, 40W, <19mΩ(10A)	17c$	Nec	MTP35N06ZL, 2SK2513, 2SK2930
2SK3296-S,-ZJ	MOS-N-FET-e*	=2SK3296:	30c$	-	MTB35N06ZL, 2SK2513-Z, 2SK2939, 2SK3051
2SK3297	MOS-N-FET-e	V-MOS, 600V, ±5A, 35W, <1,6Ω(2,5A)	17c	Nec	2SK1118, 2SK2045, 2SK2097, 2SK2118,
2SK3298	MOS-N-FET-e	V-MOS, 600V, n7,5A, 40W, <0,75Ω(5A)	17c	Nec	2SK2564, 2SK2645, 2SK2708, 2SK2740
2SK3299	MOS-N-FET-e	V-MOS, 600V, ±10A, 75W, <0,75Ω(5A)	17c$	Nec	IRFB9N60A, 2SK2866
2SK3299-S,-ZJ	MOS-N-FET-e	=2SK3299:	30c$	-	2SK2889
2SK33	N-FET	FM/VHF, 20V, Idss=2,5..20mA, Up<8V	7d	Mit,Mic	BF244..245, BFS71, 2N3822..23..
2SK330	N-FET	GenP, 50V, Idss>1,2mA, Up<0,6V	41e	Tos	2N5457, 2SK246
2SK3300	MOS-N-FET-e	V-MOS, 600V, ±20A, 155W, <0,4Ω(10A)	18c$	Nec	-
2SK3301	MOS-N-FET-e*	V-MOS, 900V, 1A, 20W, <20e(0,5A)	30c$	Tos	2SK2845
2SK3304	MOS-N-FET-e	V-MOS, 900V, ±7A, 120W, <2Ω(5A)	18c$	Nec	2SK1614, 2SK1692, 2SK2486, 2SK2674..
2SK3305	MOS-N-FET-e	V-MOS, 500V, ±5A, 75W, <1,5Ω(2,5A)	17c$	Nec	2SK1156, 2SK1246, 2SK1751, 2SK2356
2SK3305-S,-ZJ	MOS-N-FET-e	=2SK3305:	30c$	-	2SK1314, 2SK1703S, 2SK1722, 2SK1751Z..
2SK3306	MOS-N-FET-e	V-MOS, 500V, ±5A, 35W, <1,5Ω(2,5A)	17c	Nec	2SK1351, 2SK1608, 2SK1627, 2SK1993..
2SK3307	MOS-N-FET-e*	V-MOS, LogL, 60V, ±70A, 105W, <15mΩ(30A)	18c$	Nec	2SK2987
2SK331	N-FET	AF-Pre, 20V, Idss=0,06..0,8mA	-	Sanyo	-
2SK3313	MOS-N-FET-e*	V-MOS, 500V, 12A, 40W, <0,62Ω(5A)	17c	Tos	2SK2475, 2SK2842

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2SK3314	MOS-N-FET-e*	V-MOS, 500V, 15A, 150W, <0,49e(5A)	18c$	Tos	BUZ338, IRFP450, 2SK1745, 2SK2698
2SK3316	MOS-N-FET-e*	V-MOS, 500V, 5A, 35W, <1,8Ω(2,5A)	17c	Tos	2SK1232, 2SK1993, 2SK2115, 2SK2236..
2SK332	N-FET	Dual, 40V, 20mA, Idss>1,2mA, Up=0,5V	-	Sanyo	-
2SK3320	N-FET	50V, Idss<14mA, Up=0,2..1,5	-	Tos	-
2SK3322	MOS-N-FET-e*	V-MOS, 600V, ±5A, 65W, <2,2Ω(2,5A)	17c$	Nec	BUK455-600, 2SK1117, 2SK1809, 2SK1924..
2SK3322-S,-ZJ	MOS-N-FET-e*	=2SK3322:	30c$	-	2SK1625, 2SK1915, 2SK2089, 2SK2140Z
2SK3324	MOS-N-FET-e	V-MOS, 900V, ±6A, 120W, <2,8Ω(5A)	18c$	Nec	2SK1650, 2SK1794, 2SK2485, 2SK2610..
2SK3325	MOS-N-FET-e	V-MOS, 500V, ±10A, 85W, <0,85Ω(5A)	17c$	Nec	2SK1503, 2SK2186, 2SK2366
2SK3325-S,-ZJ	MOS-N-FET-e	=2SK3325:	30c$	-	2SK1865, 2SK2187, 2SK2366Z
2SK3326	MOS-N-FET-e	V-MOS, 500V, ±10A, 40W, <0,85Ω(5A)	17c	Nec	2SK2475, 2SK2714, 2SK2842, 2SK3183
2SK333	N-FET	Dual, 80V, 20mA, Idss>1,2mA, Up<3V	-	Sanyo	-
2SK3333	MOS-N-FET-e*	V-MOS, 400V, ±0,5A, 1W, <23Ω(0,5A)	9c	Mat	BSP298
2SK3337-01	MOS-N-FET-e	V-MOS, 1000V, ±7A, 255W, <2Ω(3,5A)	16c$	Fjd	-
2SK3338-01	MOS-N-FET-e	V-MOS, 500V, ±20A, 340W, <0,27Ω(10A)	16c$	Fjd	-
2SK3339-01	MOS-N-FET-e	V-MOS, 500V, ±27A, 400W, <0,2Ω(13,(A)	16c$	Fjd	-
2SK334	N-FET	=2SK331:SMD	?35f	Sanyo	-
2SK3340-01	MOS-N-FET-e	V-MOS, 400V, ±23A, 295W, <0,2Ω(11,(A)	16c$	Fjd	-
2SK3341-01	MOS-N-FET-e	V-MOS, 900V, ±10A, 310W, <1,2Ω(5A)	16c$	Fjd	-
2SK3342	MOS-N-FET-e*	V-MOS, 250V, 4,5A, 20W, <1Ω(2,5A)	30c$	Tos	MTD5N25E, IRFR234A, 2SK1920, 2SK2099
2SK334-N11	N-FET	-	35	Sanyo	→2SK334
2SK334-N12	N-FET	-	35	Sanyo	→2SK334
2SK334-N13	N-FET	-	35	Sanyo	→2SK334
2SK334-N14	N-FET	-	35	Sanyo	→2SK334
2SK3353	MOS-N-FET-e*	V-MOS, LogL, 60V, ±82A, 84W, <15mΩ(45A)	17c$	Nec	-
2SK3353-S,-Z	MOS-N-FET-e*	=2SK3353:	30c$	-	2SK3272-01(L,S)
2SK3354	MOS-N-FET-e*	V-MOS, LogL, 60V, ±83A, 100W, <13mΩ(45A)	17c$	Nec	-
2SK3354-S,-Z	MOS-N-FET-e*	=2SK3354:	30c$	-	2SK3272-01(L,S)
2SK3355	MOS-N-FET-e*	V-MOS, LogL, 60V, ±83A, 100W, <8mΩ(45A)	17c$	Nec	-
2SK3355-S,-Z	MOS-N-FET-e*	=2SK3355:	30c$	-	2SK3272-01(L,S)
2SK3356	MOS-N-FET-e*	V-MOS, LogL, 60V, ±75A, 135W, <13mΩ	18c$	Nec	2SK2987, 2SK3163
2SK3357	MOS-N-FET-e*	V-MOS, LogL, 60V, ±75A, 150W, <8mΩ	18c$	Nec	2SK2987
2SK3358	MOS-N-FET-e*	V-MOS, LogL, 100V, ±55A, 100W, <40mΩ	17c$	Nec	SPP70N10L
2SK3358-S,-Z	MOS-N-FET-e*	=2SK3358:	30c$	-	SPB70N10L
2SK3359	MOS-N-FET-e*	V-MOS, LogL, 100V, ±70A, 100W, <28mΩ	17c$	Nec	SPP70N10L
2SK3359-S,-Z	MOS-N-FET-e*	=2SK3359:	30c$	-	SPB70N10L
2SK336	MOS-N-FET-e	GenP, 50V, 0,4A, 0,6W, 12Ω	7d	Sanyo	-
2SK3360	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 35W, <40mΩ	17c	Nec	2SK3034
2SK3361	MOS-N-FET-e*	V-MOS, LogL, 100V, ±40A, 35W, <28mΩ	17c	Nec	(2SK3034)
2SK3363-01	MOS-N-FET-e*	V-MOS, LogL, 30V, ±50A, 80W, <10,5mΩ	17c$	Fjd	BUK556-60, BUZ100L, 2SK2049, 2SK2499
2SK3364-01	MOS-N-FET-e*	V-MOS, 60V, ±50A, 80W, <12mΩ(45A)	17c$	Fjd	BUK556-60, MTP52N06V, 2SK2049, 2SK2499
2SK3365(-Z)	MOS-N-FET-e*	V-MOS, LogL, 30V, ±30A, 36W, <29mΩ(10A)	30c$	Nec	IRLR2905, 2SK3025
2SK3366(-Z)	MOS-N-FET-e*	V-MOS, LogL, 30V, ±20A, 30W, <43mΩ(10A)	30c$	Nec	IRLR2705, 2SK2334, 2SK2614, 2SK2782
2SK3367(-Z)	MOS-N-FET-e*	V-MOS, LogL, 30V, ±36A, 40W, <14mΩ(10A)	30c$	Nec	IRLR2905, 2SK3025
2SK337	MOS-N-FET-e	V-MOS, Pow, 500V, ±0,1A, 10W, <100Ω(20mA)	14b&	Nec	-
2SK3377(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±20A, 30W, <70mΩ(10A)	30c$	Nec	IRLR034A, 2SK2334, 2SK2782, 2SK2869
2SK338	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, ±5A, 40W, <1,5Ω(5A)	17c$	Nec	BUZ41A..42, BUZ60, 2SK552, 2SK1246,..
2SK3385(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±30A, 30W, <45mΩ(10A)	30c$	Nec	2SK3025
2SK3386(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±34A, 35W, <40mΩ(10A)	30c$	Nec	-
2SK339	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, ±5A, 40W, <0,5Ω(5A)	17c$	Nec	BUZ30, BUZ73, IRF510, IRF512, 2SK917
2SK34	N-FET	AF/GenP, 30V, Idss>0,3mA, Up<6V	7e	Mit,Mic	BFS70, 2N3369, 2N3821, 2SK381..
2SK3402(-Z)	MOS-N-FET-e*	V-MOS, LogL, 60V, ±36A, 40W, <25mΩ(10A)	30c$	Nec	-
2SK3404	MOS-N-FET-e	V-MOS, LogL, 30V, 40A, 40W, <21mΩ	17c$	Nec	BUZ102AL, 2SK1542, 2SK1911, 2SK2513
2SK3405	MOS-N-FET-e	V-MOS, LogL, 20V, 48A, 50W, <14mΩ	17c$	Nec	BUK556-60, BUZ100L, 2SK2049, 2SK2499
2SK3408	MOS-N-FET-e*	V-MOS, LogL, int. Z-Di(G→D), 43±5V, ±1A, <0,26Ω(0,5A), 32/153nS	35a		Nec-
2SK3424	MOS-N-FET-e	V-MOS, LogL, 30V, 48A, 50W, <17mΩ	17c$	Nec	BUK556-60, BUZ100L, 2SK2049, 2SK2499
2SK343	MOS-N-FET-e	V-MOS, 140V, 8A, 100W, <0,5Ω, 100/90nS	20c$	Hit	(2SK226..227)
2SK3430	MOS-N-FET-e*	V-MOS, LogL, 40V, ±80A, 84W, <14mΩ(45A)	17c$	Nec	IRL1004, IRL2505, IRL3705N
2SK3430-S,-Z	MOS-N-FET-e*	=2SK3430:	30c$	-	IRL1004L,S, IRL2505L,S, IRL3705NL,NS
2SK3431	MOS-N-FET-e*	V-MOS, LogL, 40V, n83A, 100W, <8mΩ(45A)	17c$	Nec	IRL1004, IRL2505, IRL3705N
2SK3431-S,-Z	MOS-N-FET-e*	=2SK3431:	30c$	-	IRL1004L,S, IRL2505L,S, IRL3705NL,NS
2SK3432	MOS-N-FET-e*	V-MOS, LogL, 40V, n83A, 100W, <6mΩ(45A)	17c$	Nec	IRL1004, IRL2505, IRL3705N
2SK3432-S,-Z	MOS-N-FET-e*	=2SK3432:	30c$	-	IRL1004L,S, IRL2505L,S, IRL3705NL,NS
2SK3433	MOS-N-FET-e*	V-MOS, LogL, 60V, ±40A, 47W, <40mΩ(20A)	17c$	Nec	BUK556-60, 2SK1542, 2SK1911, 2SK2513
2SK3433-S,-Z	MOS-N-FET-e*	=2SK3433:	30c$	-	2SK2266, 2SK2290, 2SK2376, 2SK2513-Z

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2SK3434	MOS-N-FET-e*	V-MOS, LogL, 60V, ±48A, 63W, <30mΩ(20A)	17c$	Nec	BUK556-60, MTP60N06VL, 2SK2049
2SK3434-S,-Z	MOS-N-FET-e*	=2SK3434:	30c$	-	MTB52N06VL, 2SK2499-Z, 2SK2553
2SK3435	MOS-N-FET-e*	V-MOS, LogL, 60V, ±80A, 84W, <21mΩ(45A)	17c$	Nec	2SK3353, 2SK3354, 2SK3355
2SK3435-S,-Z	MOS-N-FET-e*	=2SK3435:	30c$	-	2SK3353-S,-Z, 2SK3354-S,-Z, 2SK3355-S,-Z
2SK344	MOS-N-FET-e	=2SK343: 160V	20c$	Hit	(2SK227)
2SK345	MOS-N-FET-e	V-MOS, 40V, 5A, 30W, <0,4e, 40/70nS	17c$	Hit	IRF510..513, 2SK357, 2SK463, 2SK917,..
2SK3455	MOS-N-FET-e	V-MOS, 500V, 12A, 40W, <0,6Ω	17c	NEC	2SK3184
2SK3456	MOS-N-FET-e	V-MOS, 500V, 12A, 100W, <0,6e	17c$	Nec	-
2SK3457	MOS-N-FET-e	V-MOS, 800V, 5A, 40W, <2,2Ω	17c	Nec	2SK2101
2SK3458	MOS-N-FET-e	V-MOS, 800V, 6A, 100W, <2,2Ω	17c$	Nec	BUZ305
2SK346	MOS-N-FET-e	=2SK345: 60V	17c$	Hit	IRF510..513, 2SK357, 2SK463, 2SK917,..
2SK3467	MOS-N-FET-e	V-MOS, LogL, 20V, 80A, 56W, <10mΩ	17c$	Nec	IRL1004, IRL2505, IRL3705N
2SK347(L,S)	MOS-N-FET-e	V-MOS, 400V, 1A, 10W	30c$	Hit	2SK535, 2SK579..580, 2SK945, 2SK1151,..
2SK349	MOS-N-FET-e	V-MOS, 400V, 10A, 100W, <0,9e, 70/200nS	18c$	Hit	BUZ326, BUZ351, 2SK1752, 2SK1785,..
2SK35	N-FET	GenP, 20V, 20mA, Idss<16mA, Up<1,6V	10a	Son	2N5247, 2SK186..187, 2SK363..364..
2SK350	MOS-N-FET-e	=2SK349: 450V	18c$	Hit	BUZ339, 2SK896, 2SK1752, 2SK1785,..
2SK351	MOS-N-FET-e	V-MOS, 800V, 5A, 125W, <3Ω, 100/300nS	23a$	Hit	BUZ54, BUZ84, 2SK793, 2SK1213
2SK352	MOS-N-FET-e	V-MOS, 250V, 0,3A, 8W, 30Ω	14b($)	Hit	BST78, 2SK511
2SK353	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 15GHz	52y	Nec	-
2SK354(A)	GaAs-N-FET	UHF, C-Band, 5V, 150mA, 8GHz	52y	Nec	-
2SK355	MOS-N-FET-e	V-MOS, 150V, 12A, 120W, <0,18Ω(10A)	23a$	Tos	BUZ35, 2SK401, 2SK1529
2SK356	MOS-N-FET-e	V-MOS, 250V, 12A, 120W, <0,25Ω(10A)	23a$	Tos	BUZ64, BUZ325, 2SK401, 2SK412
2SK357	MOS-N-FET-e	V-MOS, 150V, 5A, 40W, <0,9Ω(5A)	17c$	Tos	BUZ60, 2SK924, 2SK1391
2SK358	MOS-N-FET-e	V-MOS, 250V, 5A, 40W, <1Ω(5A)	17c$	Tos	BUZ60, 2SK924, 2SK1391
2SK359	MOS-N-FET-d	VHF, 20V, ±30mA, Idss>4mA, Up<2V	7f	Hit	-
2SK360	MOS-N-FET-d	=2SK359: SMD	35c, 35d	Hit	-
2SK360-D	MOS-N-FET-d	-	35	Hit	→2SK360
2SK360-E	MOS-N-FET-d	-	35	Hit	→2SK360
2SK360-F	MOS-N-FET-d	-	35	Hit	→2SK360
2SK362	N-FET	GenP, 50V, Idss>1,2mA, Up<1,5V	7a	Tos	2SK163, 2SK365
2SK363	N-FET	GenP, 40V, Idss>5mA, Up<1,2V	7a	Tos	2N5247, 2SK130, 2SK147, 2SK151, 2SK162
2SK364	N-FET	GenP, 40V, Idss>2,6mA, Up<1,5V	7a	Tos	2SK187, 2SK366
2SK365	N-FET	=2SK362:	41a	Tos	2SK163, 2SK362
2SK366	N-FET	=2SK364:	41a	Tos	2SK187, 2SK364
2SK367	N-FET	GenP, LN, 100V, Idss>0,6mA, Up<3,5V	41a	Tos	-
2SK368	N-FET	=2SK367: SMD	35e	Tos	-
2SK368-GR	N-FET	-	35	Tos	→2SK368
2SK368-O	N-FET	-	35	Tos	→2SK368
2SK368-Y	N-FET	-	35	Tos	→2SK368
2SK369	N-FET	=2SK363: ra	7a	Tos	→2SK363
2SK37	N-FET	AM/FM, 20V, Idss=0,5..6mA, Up<4,5V	24e	Nec	BFS70, 2N3821, 2SK161
2SK370	N-FET	=2SK364: ra	41a	Tos	→2SK364
2SK371	N-FET	=2SK363: ra	41a	Tos	→2SK363
2SK372	N-FET	=2SK363:	41a	Tos	→2SK363
2SK373	N-FET	=2SK367:	7a	Tos	→2SK367
2SK374	N-FET	GenP, 55V, ±30mA, Idss>1mA, Up<5V	35f	Mat	-
2SK374-P	N-FET	-	35	Mat	→2SK374
2SK374-Q	N-FET	-	35	Mat	→2SK374
2SK374-R	N-FET	-	35	Mat	→2SK374
2SK374-S	N-FET	-	35	Mat	→2SK374
2SK375	MOS-N-FET-e	V-MOS, 300V, 1A, 10W, <4Ω, 20/70nS	30c$	Hit	2SK535, 2SK945, 2SK1151, 2SK1672,..
2SK376	N-FET	AF-Pre, 20V, Idss=0,06..0,8mA	41e	Sanyo	-
2SK377	N-FET	AF-Pre, 20V, Idss=0,06..0,8mA	-	Sanyo	-
2SK378	GaAs-N-FET	UHF, 5V, 130mA, Idss>15mA, Up<4V	24f	Mat	-
2SK379	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 8A, 100W, <1,5Ω	23a$	Mat	BUZ94, 2SK278, 2SK298, 2SK554..555,..
2SK38	N-FET	Sw, GenP, 20V, Idss=0,4..5mA, Up<9V	?42f	Mit	BFS70, 2N3369, 2N3821, 2SK381..
2SK380	MOS-N-FET-e	=2SK379: 450V, <2Ω	23a$	Mat	BUZ94, 2SK554..555, 2SK636, 2SK1495,..
2SK381	N-FET	GenP, 50V, Idss>0,3mA, Up<6V	41a	Mit	2N3369
2SK382	MOS-N-FET-e	V-MOS, 500V, 2A, 30W, <4e, 25/70nS	17c$	Hit	BUZ40, BUZ74, IRF820..821, 2SK892,..
2SK383	MOS-N-FET-e	V-MOS, 100V, 10A, 50W, <0,18Ω, 60/150nS	17c$	Hit	BUZ20, BUZ72, IRF532, 2SK918, 2SK921+
2SK384	MOS-N-FET-e	V-MOS, 500V, 0,3A, 10W, <50e, 20/20nS	30c$	Hit	-
2SK385	MOS-N-FET-e	V-MOS, 400V, 10A, 120W, <0,6Ω(5A)	77c$	Tos	2SK693..694
2SK386	MOS-N-FET-e	=2SK385: 450V, <0,7Ω(5A)	77c$	Tos	2SK693..694
2SK387	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, 12A, 150W, <0,18Ω	77c$	Tos	2SK1530

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2SK388	MOS-N-FET-e	=2SK387: 250V, <0,25Ω(10A)	77c$	Tos	2SK1530
2SK389	N-FET	Dual, 50V, Idss>2,6mA, Up<2V	7-SQP/bp1	Tos	-
2SK38A	N-FET	=2SK38: Idss=0,7..7mA, Up<5V	?42f	-	BFS70, 2N3369, 2N3821, 2SK381..
2SK39(A)	N-FET	AF-Pre, LN, 20V, Idss=35..564A	10d	Son	2SK92..93, 2SK103
2SK398	MOS-N-FET-e	V-MOS, 100V, 10A, 100W, <0,25Ω(5A)	23a$	Hit	BUZ23, 2SK631, 2SK633, 2SK1529
2SK399	MOS-N-FET-e	=2SK398:	18c$	Hit	2SK631, 2SK633, 2SK1529
2SK40	N-FET	AF, LN, 50V, Idss=0,3..6,5mA, Up<5V	9a, 7e	Hit	BFS70, 2N3369, 2N3821, 2SK46, 2SK59..
2SK400	MOS-N-FET-e	V-MOS, 200V, 8A, 100W, <0,7Ω, 40/110nS	18c$	Hit	2SK412
2SK401	MOS-N-FET-e	V-MOS, 250V, 10A, 100W, <0,4Ω, 65/180nS	23a$	Hit	BUZ64, 2SK312..313, 2SK573, 2SK1401
2SK402	MOS-N-FET-e	V-MOS, 400V, 8A, 100W, <1,75Ω, 50/120nS	18c$	Hit	BUZ330..331, BUZ353..354, 2SK501
2SK403	MOS-N-FET-e	=2SK402: 450V	18c$	Hit	BUZ330..331, BUZ353..354, 2SK557
2SK404	N-FET	GenP, LN, 20V, Idss>1,2mA, Up<2V	40e	Sanyo	BC264A, BFW12, 2N4340, 2N5484..
2SK405	MOS-N-FET-e	V-MOS, Pow, 160V, 8A, 100W, <1,4Ω(5A)	18c$	Tos	2SK1529
2SK406	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 18GHz	52y	Nec	-
2SK407	GaAs-N-FET	UHF, C..Ku-Band, 5V, 120mA, 18GHz	52y	Nec	-
2SK408	MOS-N-FET-e*	V-MOS, AM-Pow, 180V, 2A, Pq>10W(28MHz)	17d*	Hit	-
2SK409	MOS-N-FET-e	=2SK408:	17f*	Hit	-
2SK41	N-FET	FM, 18V, Idss>0,6mA, Up<5V	7d	Say,Mic	BFS70, 2N3821, 2N5246, 2SK161..
2SK410	MOS-N-FET-e*	V-MOS, AM-Pow, 180V, 8A, Pep>140W(28MHz)	57y	Hit	-
2SK411	MOS-N-FET-e	V-MOS, 600V, 5A, 100W	23a$	Hit	BUZ54, BUZ84, 2SK351, 2SK793, 2SK1403+
2SK412	MOS-N-FET-e	V-MOS, 250V, 10A, 100W, <0,4Ω, 65/180nS	18c$	Hit	BUZ326, BUZ351, 2SK573, 2SK1401
2SK413	MOS-N-FET-e	V-MOS, 140V, 8A, 100W, <0,5Ω, 50/110nS	18c$	Hit	2SK400, 2SK405, 2SK631, 2SK633
2SK414	MOS-N-FET-e	=2SK413: 160V	18c$	Hit	2SK400, 2SK405, 2SK633
2SK415	MOS-N-FET-e	V-MOS, 800V, 3A, 100W, <6e, 50/120nS	18c$	Hit	BUZ307, 2SK603, 2SK954, 2SK1339
2SK416	MOS-N-FET-e	V-MOS, 40V, 2A, 10W, <0,8Ω(5A), 25/35nS	30c$	Hit	2SK462, 2SK468, 2SK1282, 2SK1973,..
2SK417	MOS-N-FET-e	V-MOS, Pow, 60V, 10A, 60W, <0,14Ω	?15c$	Tos	BUZ20, BUZ72, 2SK442, 2SK672
2SK418	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 2A, 50W, <2,2Ω	?15c$	Tos	BUZ40, IRF710, 2SK382, 2SK892
2SK419	MOS-N-FET-e	=2SK418: 450V, <2,5e	?15c$	Tos	BUZ40, 2SK382, 2SK892
2SK41NP	N-FET	=2SK41:	7f	-	-
2SK42	N-FET	AM/FM, 10V, Idss=1..5mA, Up>0,3V	10d	Son	2N5246, 2SK107, 2SK161
2SK420	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 5A, 60W, <1,4Ω	?15c$	Tos	BUZ41A..42, 2SK552..553, 2SK1440,..
2SK421	MOS-N-FET-e	=2SK420: 450V, <1,6e	?15c$	Tos	BUZ41A..42, 2SK552..553, 2SK1440,..
2SK422	MOS-N-FET-e	V-MOS, 60V, 0,7A, 0,9W, <2,8e, 17/12nS	7c(9mm)	Tos	BST70, 2SK940..941, 2SK975
2SK423	MOS-N-FET-e	V-MOS, 100V, 0,5A, 0,9W, <4,5e, 15/20nS	7c(9mm)	Tos	BSS296, 2SK941
2SK424	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 3A, 100W, <1,5Ω(5A)	23a$	Nec	BUZ53, BUZ83
2SK425	N-FET	50V, Idss>1mA, Up<1,2V	35f	Nec	-
2SK425-X11	N-FET	-	35	Nec	→2SK425
2SK425-X12	N-FET	-	35	Nec	→2SK425
2SK425-X13	N-FET	-	35	Nec	→2SK425
2SK425-X14	N-FET	-	35	Nec	→2SK425
2SK425-X15	N-FET	-	35	Nec	→2SK425
2SK425-X16	N-FET	-	35	Nec	→2SK425
2SK425-X17	N-FET	-	35	Nec	→2SK425
2SK425-X18	N-FET	-	35	Nec	→2SK425
2SK426	N-FET	=2SK425: ra	35f	Nec	-
2SK426-X21	N-FET	-	35	Nec	→2SK426
2SK426-X22	N-FET	-	35	Nec	→2SK426
2SK426-X23	N-FET	-	35	Nec	→2SK426
2SK426-X24	N-FET	-	35	Nec	→2SK426
2SK426-X25	N-FET	-	35	Nec	→2SK426
2SK426-X26	N-FET	-	35	Nec	→2SK426
2SK426-X27	N-FET	-	35	Nec	→2SK426
2SK426-X28	N-FET	-	35	Nec	→2SK426
2SK427	N-FET	AM-Pre/Mix/Osc, 15V, Idss>1,2mA, Up<1,5V	40e	Sanyo	2SK186
2SK428	MOS-N-FET-e	V-MOS, 60V, 10A, 50W, <0,15e, 60/120nS	17c$	Hit	BUZ20, BUZ72, IRF533, 2SK442, 2SK672+
2SK429(L,S)	MOS-N-FET-e	V-MOS, 100V, 3A, 20W, <0,7Ω, 35/50nS	30c$	Hit	2SK1113, 2SK1299, 2SK1254, 2SK1284
2SK43(S)	N-FET	AF/GenP, LN, 30V, Idss>0,9mA, Up<1,49V	7d, 7e	Son	2SK121, 2SK163, 2SK170, 2SK186..187..
2SK430(L,S)	MOS-N-FET-e	=2SK429: 150V, <1Ω(5A)	30c$	Hit	2SK1335
2SK431	N-FET	AF, LN, 40V, Idss>2,5mA, Up<1,5V	35f, 35a	Hit	-
2SK431-C	N-FET	-	35	Hit	→2SK431
2SK431-D	N-FET	-	35	Hit	→2SK431
2SK431-E	N-FET	-	35	Hit	→2SK431
2SK431-F	N-FET	-	35	Hit	→2SK431
2SK432	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, ±10A, 120W, <0,4Ω	23a$	Nec	BUZ45, BUZ64, 2SK401, 2SK512

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2SK433	N-FET	50V,Idss>0,3mA,Up<6V	35f	Mit	-
2SK433-B	N-FET	-	35	Mit	→2SK433
2SK433-C	N-FET	-	35	Mit	→2SK433
2SK433-D	N-FET	-	35	Mit	→2SK433
2SK433-E	N-FET	-	35	Mit	→2SK433
2SK435	N-FET	AF/HF,22V,0,1A,Idss>6mA,Up<2,5V	7d	Hit	2SK494
2SK436	N-FET	=2SK427:SMD	35f	Sanyo	2SK425
2SK436-A17	N-FET	-	35	Sanyo	→2SK436
2SK436-A18	N-FET	-	35	Sanyo	→2SK436
2SK436-A19	N-FET	-	35	Sanyo	→2SK436
2SK436-A20	N-FET	-	35	Sanyo	→2SK436
2SK436-A21	N-FET	-	35	Sanyo	→2SK436
2SK436-A22	N-FET	-	35	Sanyo	→2SK436
2SK437	GaAs-N-FET	UHF,6V,Idss>20mA,Up<3,5V,12GHz	52y	Mat	-
2SK438	GaAs-N-FET	UHF,6V,Idss>20mA,Up<3,5V,12GHz	52y	Mat	-
2SK439	MOS-N-FET-d	FM/VHF,20V,30mA,Idss>4mA,Up<2V	41f	Hit	-
2SK44	N-FET	AF,LN,20V,Idss=0,06..0,3mA,Up<4V	77e	Sanyo	-
2SK440	MOS-N-FET-e	V-MOS,200V,6A,40W,<0,5Ω,40/110nS	17c$	Hit	BUZ30,BUZ73,2SK741,2SK1319..20,..
2SK441	MOS-N-FET-e	V-MOS,500V,0,3A,0,75W,<50e	2a$	Hit	(2SK384)
2SK442	MOS-N-FET-e	V-MOS,Pow,70V,10A,30W,<0,4Ω	17c$	Tos	BUZ20,BUZ72,2SK740,2SK918
2SK443	N-FET	=2SK444:SMD	35f	Sanyo	BF512..513,2SK322
2SK443-AJ5	N-FET	-	35	Sanyo	→2SK443
2SK443-AJ6	N-FET	-	35	Sanyo	→2SK443
2SK443-AJ7	N-FET	-	35	Sanyo	→2SK443
2SK444	N-FET	Camera,LN,15V,Idss=5..38mA,Up<2V	40e	Sanyo	BC264C..D,BF410C .D,2SK147,2SK168
2SK445	N-FET	=2SK444:	7d	Sanyo	BC264C..D,BF410C..D,2SK147,2SK168
2SK446	MOS-N-FET-e	V-MOS,Pow,20V,±2A,20W,<0,5Ω(5A)	30c$	Nec	2SK416,2SK973,2SK1763
2SK447	MOS-N-FET-e	V-MOS,Pow,250V,±15A,150W,<0,24Ω(10A)	77c$	Tos	2SK678,2SK693
2SK448	MOS-N-FET-e	V-MOS,Sw,Pow,250V,±10A,120W,<0,5Ω	23a$	Nec	BUZ64,2SK312,2SK401
2SK449	MOS-N-FET-e	V-MOS,Sw,Pow,450V,±8A,120W,<1,25Ω	23a$	Nec	BUZ45,2SK312,2SK512
2SK44SP	N-FET	=2SK44:	41b	-	-
2SK45	N-FET	AF/HF,22V,Idss=0,5..6mA,Up<4,5V	5m+	Nec	BFS70,2N3369,2N3821,2N4220,2SK104..
2SK453	MOS-N-FET-e	V-MOS,VHF-Pow,100V,10A,Pq=120W(100MHz)	57y	Nec	-
2SK454	MOS-N-FET-e	V-MOS,VHF-Pow,200V,8A,Pq=140W(100MHz)	57y	Nec	-
2SK455	N-FET	=2SK456:SMD	?35f	Tos	-
2SK456	N-FET	AF-Pre,20V,Idss>0,06mA,Up<0,8V	-	Tos	-
2SK457	GaAs-N-FET	UHF,5V,120mA,Idss>20mA,Up<5V,3GHz	25za	Hit	-
2SK458	MOS-N-FET-e	V-MOS,150V,±1A 16W(Tc=25°),<1,5Ω	2a$	Nec	-
2SK459	MOS-N-FET-e	V-MOS,Pow,200V,±10A,60W,<0,5Ω(5A)	17c$	Nec	BUZ31..32,2SK890,2SK925,2SK1393,..
2SK46	N-FET	AF-Pre,LN,30V,Idss=0,3..3mA,Up<5V	41e	Mit	BFS70,2N3369,2N3821,2N4220,2SK59,..
2SK462	MOS-N-FET-e	V-MOS,Pow,60V,±2A,20W,<0,5Ω(5A)	30c$	Nec	2SK468,2SK612,2SK973,2SK1282
2SK463	MOS-N-FET-e	V-MOS,Pow,60V,±5A,40W,<0,3Ω(5A)	17c$	Nec	2SK294..295,2SK346,2SK357,2SK917
2SK464	MOS-N-FET-e	V-MOS,Pow,60V,±8A,50W,<0,2Ω(5A)	17c$	Nec	IRF521,IRF523,2SK470,2SK993
2SK468	MOS-N-FET-e	V-MOS,Pow,100V,±2A,20W	30c$	Nec	2SK429..430,2SK612,2SK1113,2SK1299,..
2SK47	N-FET	GenP,20V,Idss=0,5..6mA,Up<4,5V	7e	Nec	BPS70,2N3369,2N3821,2N4220,2SK104..
2SK470	MOS-N-FET-e	V-MOS,Pow,100V,±8A,50W,<0,3Ω(5A)	17c$	Nec	BUZ30,BUZ73,IRF520,IRF522
2SK477	MOS-N-FET-e	V-MOS,Pow,250V,±8A,60W,<0,8Ω(5A)	17c$	Nec	2SK1319..20,2SK1400,2SK1667
2SK479	MOS-N-FET-e	V-MOS,Sw,Pow,250V,±15A,100W,<0,4Ω	16c$	Nec	2SK559,2SK573,2SK1135,2SK1401
2SK48	N-FET	AF,LN,20V,Idss=0,3..3mA,Up<2,3V	5g	Tos	BF410A,2N4339,2N5358,2SK193..
2SK482	MOS-N-FET-e	V-MOS,Sw,Pow,450V,±5A,50W,<2Ω(5A)	17c$	Nec	BUZ41A..42,IRF830,2SK1246,2SK1440..
2SK484	MOS-N-FET-e	V-MOS,Sw,Pow,450V,±8A,100W,<1Ω	16c$	Nec	BUZ330..331,2SK559,2SK634,2SK1488,..
2SK49	N-FET	AM/FM,20V,Idss=0,5..6mA,Up<2,5V	7f	Nec	BF410A,2SK193,2SK195,2SK212
2SK490	MOS-N-FET-e	V-MOS,Sw,Pow,400V,±10A,100W,<0,8Ω	16c$	Nec	BUZ325..326,2SK559,2SK634,2SK1488,..
2SK492	N-FET	GenP,50V,Idss>1mA,Up<2V	35f	Mit	-
2SK492-C	N-FET	-	35	Hit	→2SK492
2SK492-D	N-FET	-	35	Hit	→2SK492
2SK492-E	N-FET	-	35	Hit	→2SK492
2SK493	N-FET	GenP,15V,Idss>5mA,Up<2,2V	7d	Sanyo	BC264C..D,BF410C..D,2SK147,2SK168
2SK494	N-FET	=2SK435:	41a	Hit	→2SK435
2SK495	MOS-N-FET-e	V-MOS,Pow,60V,5A,40W,<0,3Ω,30/40nS	17c$	Mat	2SK346,2SK463,2SK917,2SK920
2SK496	MOS-N-FET-e	=2SK495:Iso	17c	Mat	BUK441-60,2SK499,2SK705,2SK1255
2SK497	MOS-N-FET-e	V-MOS,Pow,50V,5A,40W,<0,25Ω,30/40nS	17c$	Mat	2SK346,2SK463,2SK917,2SK920
2SK498	MOS-N-FET-e	=2SK497:	30	Mat	2SK1059,2SK1112,2SK1471,2SK1719,..
2SK499	MOS-N-FET-e	=2SK497:Iso	17c	Mat	BUK441-60,2SK496,2SK705,2SK1255

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2SK50	N-FET	AF-Pre, LN, 10V, Idss=0,07..1mA	7e	Mat,Mic	2N3367, 2N4117..18, 2SK92..93, 2SK103,..
2SK500	MOS-N-FET-e	V-MOS, Pow, 60V, 10A, 80W, <0,12Ω	18c$	Mat	2SK399, 2SK631
2SK501	MOS-N-FET-e	V-MOS, Pow, 400V, 8A, 80W, <1,2Ω, 55/40nS	18c$	Mat	BUZ330..331, BUZ385
2SK502	MOS-N-FET-e	V-MOS, Pow, 400V, 3A, 40W, <4Ω, 35/15nS	17c$	Mat	BUZ76, 2SK310..311, 2SK1244
2SK503	MOS-N-FET-e	=2SK502: Iso	17c	Mat	BUK445-450, 2SK1444, 2SK1862..63,..
2SK505	N-FET	Vid, 15V, Idss>10mA, Up<3,5V	7d	Nec	2SK507
2SK507	N-FET	=2SK505:	40a	Nec	2SK505
2SK508	N-FET	=2SK505: SMD	35f	Nec	-
2SK508-K51	N-FET	-	35	Nec	→2SK508
2SK508-K52	N-FET	-	35	Nec	→2SK508
2SK508-K53	N-FET	-	35	Nec	→2SK508
2SK511	MOS-N-FET-e*	V-MOS, Vid, 250V, 0,3A, 8W, <50Ω(0,5A)	14b($)	Hit	-
2SK512	MOS-N-FET-e	V-MOS, 500V, 12A, 125W, <0,65e, 75/300nS	23a$	Hit	BUZ45, 2SK1785
2SK513	MOS-N-FET-e	V-MOS, 800V, 3A, 60W, <6e, 50/120nS	17c$	Hit	BUK456/800, 2SK1600..1601, 2SK1638,..
2SK514	N-FET	Sw, 50V, 20mA, Idss>1mA, Up<4,5V	40a	Nec	-
2SK515	N-FET	=2SK514: SMD	35f	Nec	-
2SK515-X31	N-FET	-	35	Nec	→2SK515
2SK515-X32	N-FET	-	35	Nec	→2SK515
2SK515-X33	N-FET	-	35	Nec	→2SK515
2SK515-X34	N-FET	-	35	Nec	→2SK515
2SK515-X35	N-FET	-	35	Nec	→2SK515
2SK518	N-FET	AM-Tuner, 30V, 0,05A, Idss>30mA, Up<9V	7a	Nec	BF244C, BF245C, 2SK519
2SK519	N-FET	=2SK518:	40a	Nec	BD244C, BF245C, 2SK518
2SK520	N-FET	=2SK518: SMD	35f	Nec	BF545C
2SK520-K41	N-FET	-	35	Nec	→2SK520
2SK520-K42	N-FET	-	35	Nec	→2SK520
2SK520-K43	N-FET	-	35	Nec	→2SK520
2SK520-K44	N-FET	-	35	Nec	→2SK520
2SK520-K45	N-FET	-	35	Nec	→2SK520
2SK521	N-FET	FM/VHF-Mix/Osc, 18V, Idss>2mA, Up<5,5V	41f	Hit	2SK107, BFS71, 2N3822
2SK522	N-FET	FM/VHF-Mix/Osc, 30V, Idss>4mA, Up<3V	41f	Hit	BF410C
2SK523	N-FET	AF, LN, 50V, 30mA, Idss>1mA, Up<1,2V	7d	Nec	-
2SK525	MOS-N-FET-e	V-MOS, 150V, 10A, 40W, <0,28Ω(5A)	17c	Tos	2SK1035..1036
2SK526	MOS-N-FET-e	V-MOS, 250V, 10A, 40W, <0,6Ω(5A)	17c	Tos	2SK1036, 2SK1762
2SK527	MOS-N-FET-e	V-MOS, 60V, 10A, 40W, <0,14Ω(5A)	17c	Tos	BUK442/60, 2SK1033, 2SK1093, 2SK1974,..
2SK528	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 2A, 30W, <2,2Ω(5A)	17c	Toshiba	BUK444-400, 2SK1833, 2SK1988..89,..
2SK529	MOS-N-FET-e	=2SK528: 450V, <2,6Ω(5A)	17c	Tos	BUK444-450, 2SK1833, 2SK1988..89,..
2SK530	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 5A, 40W, <1,4Ω(5A)	17c	Toshiba	2SK1231..32, 2SK1608, 2SK1990..91,..
2SK531	MOS-N-FET-e	=2SK530: 450V, <1,6Ω(5A)	17c	Tos	2SK1231..32, 2SK1608, 2SK1990..91,..
2SK532	MOS-N-FET-e	V-MOS, 60V, 12A, 40W, <0,085Ω(5A)	17c	Tos	BUK445-100, 2SK1094, 2SK1419
2SK533	N-FET	=2SK523: Idss<100pA	7d	Nec	-
2SK534	MOS-N-FET-e	V-MOS, 800V, 5A, 100W, <4e, 75/220nS	18c$	Hit	BUZ355..358, 2SK695, 2SK793, 2SK1341,..
2SK535(L,S)	MOS-N-FET-e	V-MOS, 400V, 1,5A, 20W, <6e, 20/45nS	30c$	Hit	2SK579..80, 2SK945, 2SK1151..52, 2SK1672
2SK536	MOS-N-FET-e	Analog-Sw, 50V, 100mA, 20Ω	35e	Sanyo	-
2SK537	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 1A, 60W, <9Ω(0,5A)	17c$	Tos	BUZ50, 2SK1199, 2SK1338
2SK538	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 100W, <4,5Ω(1,5A)	18c$	Tos	BUZ357..358, 2SK794, 2SK1339
2SK539	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 5A, 150W, <2,5Ω(5A)	77c$	Tos	-
2SK54	N-FET	FM-Preamp/Mix, 15V, Idss=0,8..5mA, Up<5,5V	9f,7f	Hit	BF410A, BFS70, 2N3821, 2SK212,..
2SK541	N-FET	Video-Camera, 12V, Idss>14mA, Up<2,5V	35f	Hit	-
2SK541-BIQ	N-FET	-	35	Hit	→2SK541
2SK541-BIR	N-FET	-	35	Hit	→2SK541
2SK541-BIS	N-FET	-	35	Hit	→2SK541
2SK542	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, ±2A, 25W, <1,5Ω(5A)	17c$	Nec	IRF612..613, 2SK923
2SK543	MOS-N-FET-d	-	35	Sanyo	→2SK543
2SK544	MOS-N-FET-d	FM/VHF, 20V, 30mA, Idss>1,2mA, Up<2,5V	40e,d	Sanyo	2SK192
2SK545	N-FET	=2SK546: SMD	35f	Sanyo	-
2SK545-B10	N-FET	-	35	Sanyo	→2SK545
2SK545-B11	N-FET	-	35	Sanyo	→2SK545
2SK545-B12	N-FET	-	35	Sanyo	→2SK545
2SK546	N-FET	Hi-ohm, 40V, Idss>0,03mA, Up<4V	40e	Sanyo	-
2SK549	MOS-N-FET-e	V-MOS, 60V, 10A, 50W, <0,15e, 55/100nS	17c$	Hit	BUZ20, BUZ72, IRF532..33, 2SK1114,..
2SK55	N-FET	FM-Preamp/Mix, 18V, Idss=3..14mA, Up<5,5V	9f,7f	Hit	BF244..245, BFS71, 2N3822..23, 2SK107,..
2SK550	MOS-N-FET-e	V-MOS, 60V, 25A, 75W, <0,045e, 115/245nS	17c$	Hit	BUZ21, IRF541, IRF543, 2SK1115..16,..
2SK551	MOS-N-FET-e*	V-MOS, 120V, 10A, 50W, <0,2Ω, 55/100nS	17c$	Hit	BUZ31..32, 2SK459, 2SK720, 2SK890

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2SK552	MOS-N-FET-e*	V-MOS, 450V, 5A, 50W, <1,4e, 45/115nS	17c$	Hit	BUZ41..42, BUZ90, IRF830, 2SK1246,..
2SK553	MOS-N-FET-e*	=2SK552: 500V	17c$	Hit	BUZ41..42, BUZ90, IRF830, 2SK1246,..
2SK554	MOS-N-FET-e*	V-MOS, 450V, 7A, 60W, <0,85e, 65/155nS	17c$	Hit	BUK657-500, IRF840, 2SK894, 2SK1496,..
2SK555	MOS-N-FET-e*	=2SK554: 500V, <1Ω(5A)	17c$	Hit	BUK657-500, IRF840, 2SK894, 2SK1496,..
2SK556	MOS-N-FET-e*	V-MOS, 450V, 12A, 100W, <0,55Ω(5A)	18c$	Hit	2SK725, 2SK899, 2SK1610, 2SK1745,..
2SK557	MOS-N-FET-e*	=2SK556: 500V, <0,6Ω(5A)	18c$	Hit	2SK725, 2SK899, 2SK1610, 2SK1745,..
2SK558	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 12A, 100W, 85/300nS	18c$	Hit	2SK557, 2SK560, 2SK1516, 2SK1753,..
2SK559	MOS-N-FET-e*	V-MOS, 450V, 15A, 100W, <0,36Ω(5A)	18c$	Hit	2SK725, 2SK899, 2SK1745, 2SK1757,..
2SK56	N-FET	FM/VHF, 10V, Idss=0,7..10mA, Up<4V	7f	Mat,Mic	BF410A, BFS70, 2N3821, 2SK161..
2SK560	MOS-N-FET-e*	=2SK559: 500V, 0,4Ω(5A)	18c$	Hit	2SK725, 2SK899, 2SK1745, 2SK1757,..
2SK561	MOS-N-FET-e	V-MOS, 100V, 30A, 150W, <0,07Ω	23a$	Hit	BUZ24, 2N6764, 2SK906, 2SK1303,..
2SK562	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 39A, 125W, <0,04Ω	18c($)	Fjd	BUZ347..348, 2SK857, 2SK905, 2SK1124,..
2SK564	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 32A, 125W, <0,06Ω	18c($)	Fjd	BUZ349, 2SK906, 2SK1303, 2SK1433
2SK565	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 9,6A, 125W, <0,6Ω	18c($)	Fjd	2SK557, 2SK637, 2SK1516, 2SK1753,..
2SK566	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 2,9A, 78W, <4Ω	18c($)	Fjd	2SK415, 2SK538, 2SK603, 2SK762
2SK568	MOS-N-FET	V-MOS, Sw, Pow, 450V, ±8A, 150W, <0,75Ω	77c($)	Tos	-
2SK569	GaAs-N-FET-d	UHF, C..Ku-Band, 6V, Idss>15mA, Up<2V	52y	Nec	-
2SK57	N-FET	20V, 20mA, Idss=0,5..6mA, Up<4V	35f	Nec	BF510, 2SK160
2SK570(S)	GaAs-N-FET-d	UHF, C..Ku-Band, 6V, Idss>12mA, Up<2V	52y	Nec	-
2SK571	GaAs-N-FET-d	UHF, ..C-Band, 5V, Idss=30..150mA	52y	Nec	-
2SK57-1	N-FET	-	35	Nec	→2SK57
2SK572	MOS-N-FET-e	V-MOS, 150V, 15A, 100W, <0,18Ω(10A)	18c$	Tos	BUZ350, 2SK622, 2SK1267, 2SK1491,..
2SK57-2	N-FET	-	35	Nec	→2SK57
2SK573	MOS-N-FET-e	V-MOS, 250V, 15A, 100W, <0,32Ω(10A)	18c$	Tos	BUZ323, 2SK944, 2SK1401, 2SK1641,..
2SK57-3	N-FET	-	35	Nec	→2SK57
2SK575	GaAs-N-FET-d	UHF, Ku-Band, 5V, Idss>5, Up<3V, 12GHz	52y	Son	-
2SK578	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, ±15A, 120W, <0,22Ω	77c$	Tos	-
2SK579(L,S)	MOS-N-FET-e*	V-MOS, 450V, 1,5A, 20W, <5,5e, 28/48nS	30c$	Hit	2SK1151..52, 2SK1672
2SK58	N-FET	Dual, 27V, Idss=1..16,5mA, Up<4,95V	6-DIP/bo	Son	-
2SK580(L,S)	MOS-N-FET-e*	=2SK579: 500V, <6Ω(5A)	30c$	Hit	2SK1152, 2SK1672
2SK581	N-FET	HF, LN 30V, Idss>0,9mA, Up<1,49V	41e	Son	-
2SK582	N-FET	VHF/UHF, 30V, Idss>40mA, Up<6V, 500MHz	41e	Son	-
2SK583	MOS-N-FET-e	V-MOS, Analog-Sw, 50V, 0,2A, 0,6W, 20e	7d	Sanyo	BSS100, BST72
2SK585	GaAs-N-FET-d	UHF, X-Band, 5V, Idss>20mA, Up<4V, 12GHz	25	Son	-
2SK586	GaAs-N-FET-d	UHF, Ku-Band, 5V, Idss>2mA, Up<3V, 12GHz	52y	Son	-
2SK587	GaAs-N-FET-d	UHF, X-Band, 5V, Idss>2mA, Up<3V, 12GHz	25	Son	-
2SK59	N-FET	AF-Pre, LN, 30V, Idss=0,3..1,4mA, Up<5V	9a	Hit	BFS70, 2N3821, 2N4220, 2SK46, 2SK104,..
2SK590	GaAs-N-FET-d	VHF/UHF, 10V, Idss>20mA, Up<4V, 1GHz	25za	Tos	-
2SK591	MOS-N-FET-e	V-MOS, LogL, 60V, ±15A, 35W, <55mΩ(5A)	17c	NEC	2SK1094
2SK593	GaAs-N-FET-d	VHF/UHF, 5V, Idss>15mA, Up<4V, 800MHz	25zb	Mat	-
2SK595	N-FET	=2SK596: SMD	?35f	Sanyo	-
2SK595-20	N-FET	-	35	Sanyo	→2SK595
2SK595-21	N-FET	-	35	Sanyo	→2SK595
2SK595-22	N-FET	-	35	Sanyo	→2SK595
2SK595-23	N-FET	-	35	Sanyo	→2SK595
2SK595-24	N-FET	-	35	Sanyo	→2SK595
2SK596	N-FET	Cond.-microphone amp, 20V, Idss>0,1..0,8mA	41e	Sanyo	KSK596
2SK597	N-FET	=2SK596	-	Sanyo	-
2SK60	N-FET	V-FET-Pow, 170V, 5A, 63W, 16Ω	23a$	Son	-
2SK600	MOS-N-FET-e	V-MOS, 60V, 25A, 75W, <0,055e	17c$	Hit	BUZ21, IRF540..543, 2SK942, 2SK1115,..
2SK601	MOS-N-FET-e	V-MOS, Sw, 80V, ±0,5A, 1W, <4Ω, 15/20nS	39b	Mat	BST80, 2SK1078..1079
2SK602	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 1A, 40W, <8Ω	17c	Matsushita	BUZ78, 2SK537
2SK603	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 80W, <5Ω	16c($)	Mat	BUZ307, 2SK415, 2SK954
2SK604	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 5A, 80W, <3,5Ω	16c($)	Mat	BUZ355..357, 2SK534, 2SK695, 2SK793,..
2SK606	N-FET	FM-Tuner, 30V, 20mA, Idss>0,5mA, Up<3V	7f	Mat	2SK193, 2SK195
2SK607	N-FET	=2SK606;	40d	Mat	2SK193, 2SK195
2SK608	N-FET	=2SK606: SMD	35c	Mat	(2SK238)
2SK608-P	N-FET	-	35	Mat	→2SK608
2SK608-Q	N-FET	-	35	Mat	→2SK608
2SK608-R	N-FET	-	35	Mat	→2SK608
2SK608-S	N-FET	-	35	Mat	→2SK608
2SK609	GaAs-N-FET-d	UHF, C..Ku-Band, 6V, Idss>20mA, Up<3,5V	51y	Nec	-
2SK61	N-FET	FM/VHF, 18V, Idss=1..10mA, Up<4V	7d	Tos	BF244A..245A, BFS71, 2N3822..23..
2SK610	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 3A, 80W, <4Ω	16c($)	Mat	BUZ307, 2SK415, 2SK635, 2SK954

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2SK611(Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, ±1A 10W, <5Ω(0,5A)	30c$	Nec	2SK468
2SK612(Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, ±2A, 20W, <0,45Ω(5A)	30c$	Nec	2SK468, 2SK429..430, 2SK1283
2SK613	N-FET	Camera, 15V, Idss>13,4mA, Up<2V	35f	Son	-
2SK613-2	N-FET	-	35	Son	→2SK613
2SK613-3	N-FET	-	35	Son	→2SK613
2SK613-4	N-FET	-	35	Son	→2SK613
2SK614	MOS-N-FET-e	V-MOS, 80V, ±0,5A, 0,75W, <4e, 15/20nS	7c	Mat	BST70, 2SK423, 2SK940..941
2SK615	MOS-N-FET-e	=2SK614: 1W	9c	Mat	BST70, 2SK423, 2SK940..941
2SK616	MOS-N-FET-e	V-MOS, Sw, Pow, 200V, 22A, 125W, <0,12Ω	18c$	Fjd	BUZ350, 2SK1491, 2SK2007, 2SK2058,..
2SK617	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 1A, 40W, <8Ω	-	Mat	-
2SK618	GaAs-N-FET-d	VHF/UHF, 10V, Idss>20mA, Up<4V	35e	Tos	-
2SK619	MOS-N-FET-e*	V-MOS, HF, Vid., 70V, 0,3A, 10W	14f*, b$	Hit	-
2SK620	MOS-N-FET-e	V-MOS, 50V, ±0,1A, Int.Di (S>G)	35a	Mat	-
2SK621	MOS-N-FET-e	int.Di+R (S>G), V-MOS, 20V, ±0,1A	35a	Mat	-
2SK622	MOS-N-FET-e*	V-MOS, 150V, 20A, 120W, <75mΩ(10A)	18c$	Hit	BUZ350, 2SK1267, 2SK1491, 2SK2007,..
2SK623	MOS-N-FET-e*	V-MOS, 250V, 20A, 120W, <0,15Ω(10A)	18c$	Hit	2SK1491, 2SK2007, 2SK2058, 2SK2075,..
2SK624	N-FET	AF-Pre, LN, 20V, 2mA, Idss=95..385µA	40e	Mat	-
2SK625	N-FET	Condensator-Microphone, 20V, Idss>0,06mA	35f	Tos	-
2SK625-G	N-FET	-	35	Tos	→2SK625
2SK625-O	N-FET	-	35	Tos	→2SK625
2SK625-R	N-FET	-	35	Tos	→2SK625
2SK625-Y	N-FET	-	35	Tos	→2SK625
2SK626	MOS-N-FET-e	V-MOS, Sw, Pow, 30V, 20A, 80W, <0,07Ω	16c($)	Mat	BUZ350
2SK627	MOS-N-FET-e	=2SK626: 50V	16c($)	Mat	BUZ350
2SK628	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 5A, 40W, <0,4Ω	17c	Matsushita	BUK442-100, BUK542-100, 2SK992,..
2SK629	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 20A, 80W, <0,1Ω	16c($)	Mat	2SK622
2SK63	N-FET	V-FET, 120V, 0,2A, 0,47W, Up<9,5V	2a$	Son	-
2SK630	MOS-N-FET-e	V-MOS, Sw, Pow, 160V, 5A, 40W, <0,5Ω	16c($)	Mat	-
2SK631	MOS-N-FET-e	V-MOS, Sw, Pow, 160V, 10A, 80W, <0,2Ω	16c($)	Mat	2SK633
2SK632	MOS-N-FET-e	V-MOS, Sw, Pow, 200V, 5A, 40W, <1,2Ω	16c($)	Mat	-
2SK633	MOS-N-FET-e	V-MOS, Sw, Pow, 200V, 10A, 80W, <0,25Ω	16c($)	Mat	2SK412
2SK634	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 10A, 80W, <0,7Ω	16c($)	Mat	BUZ326, BUZ351, 2SK559
2SK635	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 3A, 40W, <4,5Ω	16c($)	Mat	BUZ307, 2SK415, 2SK954
2SK636	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 8A, 80W, <1,4Ω	16c($)	Mat	BUZ330..331, BUZ353..354
2SK637	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 80W, <1,4Ω	16c($)	Mat	2SK557, 2SK644, 2SK1488, 2SK1753,..
2SK638	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 80W, <5Ω	18c$	Mat	BUZ307, 2SK415, 2SK538, 2SK603
2SK641	MOS-N-FET-e*	V-MOS, 450V, 10A, 100W, <0,8Ω(5A)	18c$	Hit	BUZ339, 2SK896, 2SK1488, 2SK1752,..
2SK642	MOS-N-FET-e*	=2SK641: 500V, <1Ω(5A)	18c$	Hit	BUZ339, 2SK896, 2SK1488, 2SK1753,..
2SK643	MOS-N-FET-e	V-MOS, 450V, 10A, 125W, <0,8Ω(5A)	18c$	Tos	BUZ339, 2SK896, 2SK1488, 2SK1752,..
2SK644	MOS-N-FET-e	=2SK643: 500V, <1Ω(5A)	18c$	Tos	BUZ339, 2SK896, 2SK1488, 2SK1753,..
2SK645	N-FET	Microphone Amplifier, 15V, Zin>200Me, Ur<40mV	-	Tos	-
2SK646	MOS-N-FET-e	V-MOS, 1200V, 4A, 125W, <4Ω, 80/350nS	23a$	Hit	-
2SK647	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 12GHz	51y	Mat	-
2SK648	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 12GHz	51y	Mat	-
2SK649	GaAs-N-FET	UHF, Ku-Band, 6V, 0,1A, 12GHz	51y	Mat	-
2SK65	N-FET	AF-Pre, LN, 12V, 2mA, Idss=0,04..0,8mA	9e	Mat	-
2SK650	GaAs-N-FET	UHF, 6V, 120mA, Idss=20..120mA, 4GHz	25za	Mat	-
2SK651	GaAs-N-FET	UHF, 6V, 150mA, Idss=40..150mA, 4GHz	25za	Mat	-
2SK652	N-FET	=2SK301:	40e	Mat	→2SK301
2SK653	GaAs-N-FET	UHF, 5V, 70mA, 800MHz	44	Mat	-
2SK654(Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, ±1A 10W, <3Ω(0,5A)	30c$	Nec	2SK468, 2SK611..612
2SK655	MOS-N-FET-e	=2SK620:	40c	Mat	-
2SK656	MOS-N-FET-e	=2SK621:	40c	Mat	-
2SK657	MOS-N-FET-e	=2SK620:	9c	Mat	-
2SK658	MOS-N-FET-e	=2SK621:	9c	Mat	-
2SK659	MOS-N-FET-e	V-MOS, LogL, 60V, ±12A, 35W, <75mΩ(5A)	17c	NEC	2SK1033, 2SK1093, 2SK1256, 2SK1344
2SK66	N-FET	AF, LN, 55V, Idss>0,3mA, Up<5V	7e	Mat, Mic	BFS70, 2N3821, 2N4220, 2SK59, 2SK104,..
2SK660	N-FET	Cond.-microphone amp, 20V, 10mA	40a	Nec	-
2SK662	N-FET	-	35(2mm)	Mat	→2SK662
2SK662-P	N-FET	-	35(2mm)	Mat	→2SK662
2SK662-Q	N-FET	-	35(2mm)	Mat	→2SK662
2SK662-R	N-FET	-	35(2mm)	Mat	→2SK662
2SK663	N-FET	-	35(2mm)	Mat	→2SK663
2SK663-P	N-FET	-	35(2mm)	Mat	→2SK663

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2SK663-Q	N-FET	-	35(2mm)	Mat	→2SK663
2SK663-R	N-FET	-	35(2mm)	Mat	→2SK663
2SK663-S	N-FET	-	35(2mm)	Mat	→2SK663
2SK664	MOS-N-FET-e*	-	35(2mm)	Mat	→2SK664
2SK665	MOS-N-FET-e*	-	35(2mm)	Mat	→2SK665
2SK666	GaAs-N-FET	VHF/UHF, 4V, 150mA, Idss>20mA, 900MHz	25za	Hit	-
2SK667	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 8A, 80W, <1,5Ω	16c($)	Mat	BUZ330..331, BUZ353..354, 2SK501
2SK668	GaAs-N-FET	-	44	Hit	→2SK668
2SK669	MOS-N-FET-e	V-MOS, Analog-Sw, 50V, 0,1A, 0,2W, 20e	40e,d	Sanyo	BSS100
2SK67(A)	N-FET	20V, Idss=0,02..1mA, Up<0,8V	?35b	Nec	-
2SK671	GaAs-N-FET	UHF, X-Band, 5,5V, 120mA, 12GHz	2S	Son	-
2SK672	MOS-N-FET-e	V-MOS, 60V, 10A, 40W, <0,2Ω(5A)	17c$	Tos	BUZ20, IRF532..533, 2SK918, 2SK1114,..
2SK67-2	N-FET	-	35	Nec	→2SK67
2SK673	MOS-N-FET-e	V-MOS, 60V, 15A, 75W, <0,11Ω(5A)	17c$	Tos	BUZ21, IRF530..531, 2SK971, 2SK1416,..
2SK67-3	N-FET	-	35	Nec	→2SK67
2SK674	MOS-N-FET-e	V-MOS, 60V, 25A, 100W, <60mΩ(10A)	17c$	Tos	BUK555-60, 2SK1296
2SK67-4	N-FET	-	35	Nec	→2SK67
2SK67-5	N-FET	-	35	Nec	→2SK67
2SK676	GaAs-N-FET	UHF, K-Band, 5V, 70mA, 12GHz	52y	Son	-
2SK67-6	N-FET	-	35	Nec	→2SK67
2SK677	GaAs-N-FET	UHF, K-Band, 5V, 100mA, 12GHz	51y	Son	-
2SK67-7	N-FET	-	35	Nec	→2SK67
2SK678	MOS-N-FET-e	V-MOS, DC-DC, 500V, 13A, 150W, <0,4Ω	77c$	Tos	2SK1333
2SK67-8	N-FET	-	35	Nec	→2SK67
2SK679	MOS-N-FET-e*	V-MOS, S, 30V, n0,5A, 0,75W, <1Ω(0,5A)	7b	Nec	BST70, 2SK422, 2SK940
2SK679A	MOS-N-FET-e*	V-MOS, S, 30V, ±0,5A, 0,75W, <0,7Ω(0,5A)	7b	Nec	BST70, 2SK422, 2SK940
2SK67-AJ2	N-FET	-	?35	Nec	→2SK67
2SK67-AJ3	N-FET	-	?35	Nec	→2SK67
2SK67-AJ4	N-FET	-	?35	Nec	→2SK67
2SK67-AJ5	N-FET	-	?35	Nec	→2SK67
2SK67-AJ6	N-FET	-	?35	Nec	→2SK67
2SK67-AJ7	N-FET	-	?35	Nec	→2SK67
2SK67-J2	N-FET	-	ч35	Nec	→2SK67
2SK67-J3	N-FET	-	ч35	Nec	→2SK67
2SK67-J4	N-FET	-	ч35	Nec	→2SK67
2SK67-J5	N-FET	-	ч35	Nec	→2SK67
2SK67-J6	N-FET	-	ч35	Nec	→2SK67
2SK67-J7	N-FET	-	ч35	Nec	→2SK67
2SK67-J8	N-FET	-	ч35	Nec	→2SK67
2SK68(A)	N-FET	AF, 50V, Idss=0,5..12mA, Up<1,5V	7a	Nec	2SK106, 2SK121, 2SK163, 2SK170, 2SK184..
2SK680(A)	MOS-N-FET-e*	=2SK681: ±1A	39b	Nec	2SK1726
2SK680A	MOS-N-FET-e	-	39	Nec	→2SK680A
2SK681(A)	MOS-N-FET-e*	=2SK679: ±1A 1W	9c	Nec	2SK975, 2SK1272, 2SK1274, 2SK1733
2SK682	MOS-N-FET-e*	FREDFET, 450V, 12A, 100W, <0,55Ω(5A)	18c$	Hit	BUK638-500
2SK683	MOS-N-FET-e*	=2SK682: 500V, <0,6Ω(5A)	18c$	Hit	BUK638-500
2SK684	MOS-N-FET-e*	V-MOS, 800V, 7A, 100W, <1,5Ω(5A)	18c$	Hit	2SK1032, 2SK1358, 2SK1502, 2SK1614,..
2SK685	MOS-N-FET-e*	FREDFET, 1000V, 5A, 100W, <2Ω(5A)	18c$	Hit	BUK638-1000, BUZ380..381
2SK686	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 5A, 40W, <0,3Ω(2,5A)	17c$	Sanyo	2SK294, 2SK346, 2SK463, 2SK917,..
2SK687	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 10A, 60W, <0,18Ω(5A)	17c$	Sanyo	2SK442, 2SK549, 2SK672, 2SK970, 2SK1114
2SK688	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 15A, 60W, <0,12Ω(5A)	17c$	Sanyo	BUK552-60, 2SK673, 2SK971, 2SK1416
2SK689	GaAs-N-FET	UHF, 6V, 70mA, Idss=13..70mA, 4GHz	51y	Mat	-
2SK69	N-FET	V-FET, AF, 140V, 0,1A, 0,8W	2a$	Nec	-
2SK690	GaAs-N-FET	UHF, 2x Z-Di, 10V, 0,6A, 1GHz	39f	Mat	-
2SK691	GaAs-N-FET	UHF-Pow, 20V, 6,3A, 1GHz	-	Mat	-
2SK692	N-FET	Cond.-microphone amp, 20V, Idss>0,06mA	40a	Nec	-
2SK693	MOS-N-FET-e	V-MOS, 450V, 13A, 150W, <0,4Ω(5A)	77c$	Tos	2SK678, 2SK1333, 2SK1544
2SK694	MOS-N-FET-e	V-MOS, 500V, 12A, 150W, <0,5Ω(5A)	77c$	Tos	2SK678, 2SK1333, 2SK1544
2SK695	MOS-N-FET-e*	V-MOS, 800V, 5A, 100W, <3Ω(5A)	18c$	Hit	2SK793..94, 2SK727, 2SK1760, 2SK1794,..
2SK696	MOS-N-FET-e*	V-MOS, 1000V, 3A, 100W, <4Ω(5A)	18ca	Hit	2SK727, 2SK794, 2SK1461, 2SK1649..50,..
2SK697	GaAs-N-FET	HF, 5V, Idss=15..50mA, 50MHz	44	Mat	-
2SK698	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, ±10A, 120W, <0,6Ω	16c$	Nec	2SK556..557, 2SK642, 2SK644, 2SK683,..
2SK699	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, ±2A, 15W, <1,2Ω(5A)	14b$	Nec	2SK1284
2SK70	N-FET	V-FET-Pow, 100V, 10A, 100W, Idss=3..6A	23a$	Nec	-
2SK700	MOS-N-FET-e	=2SK699: 80V, <0,8Ω(5A)	14b$	Nec	2SK1284

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2SK701	MOS-N-FET-e	=2SK699:60V,<0,6Ω(5A)	14b$	Nec	2SK1283
2SK702	MOS-N-FET-e	V-MOS,LogL,100V,±5A,50W,<0,45Ω(5A)	17c$	Nec	2SK991
2SK703	MOS-N-FET-e	=2SK702:Iso,35W	17c	Nec	BUK542-100,2SK1260,2SK1265
2SK704	MOS-N-FET-e	V-MOS,LogL,60V,±5A,50W,<0,25Ω(5A)	17c$	Nec	2SK702,2SK991
2SK705	MOS-N-FET-e	=2SK704:Iso,35W	17c	Nec	BUK541-60,2SK1260,2SK1255
2SK707	MOS-N-FET-e	V-MOS,250V,±25A,120W,<0,15Ω(10A)	16c$	Nec	2SK623,2SK901,2SK944,2SK1641
2SK708	MOS-N-FET-e	V-MOS,Sw,Pow,450V,±10A,200W,<0,6Ω(10A)	77c$	Tos	2SK678,2SK693,2SK694,2SK1029
2SK709	N-FET	HF,AM,20V,Idss=6..32mA,Up<2,5V	7d	Tos	2SK1000
2SK71	N-FET	V-FET-Pow,160V,15W,Idss=30..300	22a$	Nec	-
2SK710	N-FET	=2SK709:	41a	Tos	-
2SK711	N-FET	=2SK709:SMD	35f	Tos	-
2SK711-BL	N-FET	-	35	Tos	→2SK711
2SK711-GR	N-FET	-	35	Tos	→2SK711
2SK711-V	N-FET	-	35	Tos	→2SK711
2SK712	MOS-N-FET-e	V-MOS,120V,10A,25W,<0,2Ω	17c	Hit	2SK1035,2SK1230,2SK2212
2SK713	MOS-N-FET-e	V-MOS,450V,4A,25W,<1,4e	17c	Hit	2SK1231..32,2SK1351,2SK1608,2SK1626..
2SK714	MOS-N-FET-e	=2SK713:500V	17c	Hit	2SK1232,2SK1351,2SK1608,2SK1627,..
2SK715	N-FET	AM-Tuner,15V,Idss=5..24mA,Up<1,4V	40e	Sanyo	-
2SK719	MOS-N-FET-e	V-MOS,Sw,Pow,900V,±5A,120W,<4Ω(5A)	16c$	Nec	2SK727,2SK1205,2SK1461,2SK1649..1650
2SK72	N-FET	Dual,VHF,20V,Idss>0,6mA,Up<3,3V	81bx	Tos	-
2SK720A	MOS-N-FET-e	V-MOS,250V,±20A,120W,<0,23Ω(10A)	16c$	Nec	2SK901,2SK944,2SK1641,2SK1673..74,..
2SK722	MOS-N-FET-e	V-MOS,Sw,Pow,170V,10A,100W	18c$	Son	2SK633
2SK723	MOS-N-FET-e	V-MOS,Sw,Pow,500V,7A,125W,<1,2Ω	18c$	Fjd	BUZ330..331,BUZ353..354,2SK1032
2SK724	MOS-N-FET-e	V-MOS,Sw,Pow,500V,10A,100W,<0,67©	18c$	Fjd	2SK642,2SK644,2SK683,2SK1753,2SK1785
2SK725	MOS-N-FET-e	V-MOS,Sw,Pow,500V,15A,125W,<0,38Ω	18c$	Fjd	BUZ338,2SK788,2SK899,2SK1610,..
2SK726	MOS-N-FET-e	V-MOS,Sw,Pow,900V,3A,100W,<5Ω(1,5A)	18c$	Fjd	2SK696,2SK1339
2SK727(-01)	MOS-N-FET-e	V-MOS,Sw,Pow,900V,5A,125W,<2,5Ω(2,5A)	18c$	Fjd	2SK685,2SK1461,2SK1760,2SK1794,..
2SK73	N-FET	AF-Pow,200V,0,1A,5W,Idss<100mA	14a$	Mat	-
2SK732	MOS-N-FET-e	V-MOS,Sw,Pow,450V,10A,45W,<0,78Ω(5A)	17c	Mitsubishi	-
2SK733	MOS-N-FET-e	=2SK732:120W	?18c$	Mit	BUZ339,2SK896,2SK1488,2SK1785..
2SK734	MOS-N-FET-e	V-MOS,Sw,Pow,450V,15A,150W,<0,52Ω(5A)	?18c$	Mit	2SK1610,2SK1678,2SK1745,2SK1757,..
2SK735	MOS-N-FET-e	V-MOS,450V,±10A,100W,<0,8Ω(5A)	18c$	Nec	BUZ339,2SK896,2SK1488,2SK1785,..
2SK736	MOS-N-FET-e	V-MOS,LogL,100V,±15A,35W,<80mΩ(5A)	17c	Nec	2SK1034,2SK1306,2SK1558
2SK737	MOS-N-FET-e	V-MOS,LogL,100V,±12A,35W,<0,15Ω(5A)	17c	Nec	2SK1035,2SK1305,2SK1558
2SK738(-Z)	MOS-N-FET-e	V-MOS,Sw,Pow,30V,±2A,20W,<0,17Ω(5A)	30c$	Nec	2SK973..74,2SK1763,2SK1973
2SK739(-Z)	MOS-N-FET-e	=2SK738:60V,<0,25Ω(5A)	30c$	Nec	2SK973..74,2SK1763,2SK1973
2SK740	MOS-N-FET-e*	V-MOS,150V,10A,50W,<0,15Ω(5A)	17c$	Hit	BUZ31..32,2SK459,2SK890,2SK925,..
2SK741	MOS-N-FET-e*	V-MOS,250V,7A,50W,<0,55Ω(5A)	17c$	Hit	2SK477,2SK1319..20,2SK1400
2SK742	MOS-N-FET-e	V-MOS,Sw,Pow,50V,5A,30W,<0,22Ω	17c	Matsushita	BUK441-60,BUK541-60,2SK499,2SK1255..
2SK743	MOS-N-FET-e	V-MOS,Sw,Pow,50V,8A,40W,<0,15Ω	17c	Matsushita	BUK542-50,BUZ72(A)F,2SK1261,2SK1556
2SK744	MOS-N-FET-e	V-MOS,Sw,Pow,50V,10A,50W,<0,12Ω	17c	Matsushita	BUZ71(A)F,BUK442-50,2SK1033,2SK1093
2SK745	MOS-N-FET-e	V-MOS,Sw,Pow,50V,20A,100W,<0,055Ω	18c$	Mat	2SK622,2SK629,2SK1267
2SK746	MOS-N-FET-e	V-MOS,Sw,Pow,50V,20A,100W,<0,055Ω	16c(S)	Mat	2SK622,2SK629,2SK1267
2SK747	MOS-N-FET-e	V-MOS,Sw,Pow,100V,5A,30W,<0,55Ω	17c	Matsushita	BUK442-100,BUK542-100,2SK1260,..
2SK748	MOS-N-FET-e	V-MOS,Sw,Pow,100V,8A,40W,<0,22Ω	17c	Matsushita	BUK443-100,BUK543-100,2SK1261..
2SK749	MOS-N-FET-e	V-MOS,Sw,Pow,100V,10A,50W,<0,18Ω	17c	Matsushita	BUK545-100,2SK1230,2SK1305,2SK1430..
2SK750	MOS-N-FET-e	V-MOS,Sw,Pow,100V,20A,100W,<0,08Ω	18c$	Mat	2SK622,2SK629,2SK1267
2SK751	MOS-N-FET-e	V-MOS,Sw,Pow,100V,20A,100W,<0,08Ω	16c$	Mat	2SK622,2SK629,2SK1267
2SK752	MOS-N-FET-e	V-MOS,Sw,Pow,160V,3A,30W,<1Ω	17c	Matsushita	BUZ73(A)F,BUK444-200,2SK1264
2SK753	MOS-N-FET-e	V-MOS,Sw,Pow,160V,5A,40W,<0,5Ω	17c	Matsushita	BUZ73(A)F,BUK444-200,2SK1265
2SK754	MOS-N-FET-e	V-MOS,Sw,Pow,160V,10A,50W,<0,22Ω	17c	Matsushita	2SK525,2SK1035
2SK755	MOS-N-FET-e	V-MOS,Sw,Pow,200V,5A,40W,<0,5Ω(5A)	17c	Matsushita	BUZ73(A)F,BUK444-200,2SK2010
2SK756	MOS-N-FET-e	V-MOS,Sw,Pow,200V,8A,40W,<0,53Ω(5A)	17c	Matsushita	BUK445-200,BUK545-200,2SK1478
2SK757	MOS-N-FET-e	V-MOS,Sw,Pow,200V,10A,50W,<0,33Ω(5A)	17c	Matsushita	2SK526,2SK1036,2SK2212
2SK758	MOS-N-FET-e	V-MOS,Sw,Pow,250V,±5A,40W,<0,7Ω(5A)	17c	Matsushita	2SK2010,2SK2345
2SK759	MOS-N-FET-e	V-MOS,Sw,Pow,250V,8A,50W,<0,4Ω(5A)	17c	Matsushita	2SK1478,2SK1568..69,2SK1668
2SK760	MOS-N-FET-e	V-MOS,Sw,Pow,250V,15A,100W,<0,22Ω	18c$	Mat	2SK573,2SK1135,2SK1401
2SK761	MOS-N-FET-e	V-MOS,Sw,Pow,250V,15A,100W,<0,22Ω	16c	Mat	2SK2012
2SK762	MOS-N-FET-e	V-MOS,Sw,Pow,400V,3A,40W,<3Ω(5A)	17c	Matsushita	BUK445-450,2SK1444;2SK1862,2SK2431..
2SK762A..765A	MOS-N-FET-e	=2SK762..765:450V	-		-
2SK763	MOS-N-FET-e	V-MOS,Sw,Pow,400V,5A,50W,<1,4Ω(5A)	17c	Matsushita	BUK445-400,2SK1231,2SK1445,2SK1992..
2SK764	MOS-N-FET-e	V-MOS,Sw,Pow,400V,10A,100W,<0,75Ω	18c$	Mat	BUZ339,2SK896,2SK1488,2SK1753,..
2SK765	MOS-N-FET-e	V-MOS,Sw,Pow,400V,10A,100W,<0,75Ω	16c	Mat	2SK1206,2SK1225,2SK1328
2SK766	MOS-N-FET-e	V-MOS,500V,3A,40W,<3,6Ω(5A)	17c	Matsushita	BUK445-500,2SK1572,2SK1767

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2SK767	MOS-N-FET-e	V-MOS, 500V, 5A, 50W, <1,8Ω(5A)	17c	Matsushita	2SK1232, 2SK1351, 2SK1608, 2SK1627..
2SK768	MOS-N-FET-e	V-MOS, 500V, 10A, 100W, <1Ω(5A)	18c$	Mat	2SK724, 2SK896, 2SK1488, 2SK1753,..
2SK769	MOS-N-FET-e	=2SK768: Iso	16c	Mat	2SK1206, 2SK1523, 2SK1832
2SK770	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 2A, 40W, <5Ω(5A)	17c	Matsushita	BUK445-600, 2SK1758, 2SK1834, 2SK1953..
2SK771	N-FET	=2SK772: SMD	35f	Sanyo	-
2SK771-3	N-FET	-	35	Sanyo	→2SK771
2SK771-4	N-FET	-	35	Sanyo	→2SK771
2SK771-5	N-FET	-	35	Sanyo	→2SK771
2SK772	N-FET	Sw, 40V, Idss=1,2..12mA, Up<2,5V	40e	Sanyo	-
2SK773	MOS-N-FET-e	V-MOS, 500V, ±12A, 120W, <0,6Ω(5A)	16c$	Nec	BUK637-500, 2SK644, 2SK896, 2SK1488
2SK774	MOS-N-FET-e	V-MOS, 500V, n18A, 120W, <0,45Ω(5A)	16c$	Nec	2SK870, 2SK1170, 2SK1518, 2SK1500,..
2SK775	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 2A, 50W, <3,5Ω(5A)	17c$	Sanyo	BUZ74, IRF820, IRF822, 2SK892
2SK776	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 5A, 60W, <1,6Ω(5A)	17c$	Sanyo	BUZ41A..42, 2SK1246, 2SK1440, 2SK1751..
2SK777	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 10A, 120W, <0,65Ω(5A)	18c$	Sanyo	BUZ339, 2SK644, 2SK683, 2SK1488,..
2SK778	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 0,5A, 10W, <9Ω(0,25A)	17c$	Sanyo	2SK296, 2SK1052
2SK779	GaAs-N-FET	SHF, 5V, 0, 12A, 20..120mA, 12GHz	51y	Hit	-
2SK780	GaAs-N-FET	SHF, 5V, 0, 12A, Idss=20..120mA, 12GHz	51y	Hit	-
2SK782	MOS-N-FET-e	V-MOS, Sw, Pow, 200V, 5A, 40W, <0,5Ω(5A)	30c$	Mat	(2SK924, 2SK1391)
2SK783	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 12A, 125W, <0,57Ω	-	Fjd	-
2SK784	MOS-N-FET-e	V-MOS, 450V, ±20A, 150W, <0,35Ω(10A)	18c$	Nec	2SK868A, 2SK870, 2SK1517..18, 2SK1680,..
2SK785	MOS-N-FET-e	=2SK784: 500V, <0,4Ω(10A)	18c$	Nec	2SK870, 2SK1500, 2SK1518, 2SK1680,..
2SK786	MOS-N-FET-e	V-MOS, 900V, ±3A, 60W, <7,5Ω(1,5A)	17c$	Nec	BUK456-1000, 2SK792, 2SK1793
2SK787	MOS-N-FET-e	V-MOS, 900V, ±8A, 150W, <1,6Ω(5A)	18c$	Nec	2SK1358, 2SK1502, 2SK1614, 2SK1692
2SK788	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 13A, 150W, <0,5Ω(5A)	18c$	Tos	2SK560, 2SK725, 2SK1610, 2SK1745,..
2SK789	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 15A, 150W, <0,7Ω(5A)	18c$	Tos	2SK559..560, 2SK725,, 2SK1610, 2SK1745..
2SK79	N-FET	V-FET, AF, 120V, 0,2A, 0,75W	7c(9mm)	Son	-
2SK790	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 15A, 150W, <0,4Ω(5A)	18c$	Tos	2SK560, 2SK725, 2SK1610, 2SK1745,..
2SK791	MOS-N-FET-e	V-MOS, 850V, 3A, 100W, <4,5Ω(1,5A)	17c$	Tos	BUK456-1000, 2SK1456, 2SK1601, 2SK1638..
2SK792	MOS-N-FET-e	=2SK791: 900V	17c$	Tos	BUK456-1000, 2SK1456, 2SK1601, 2SK1638..
2SK793	MOS-N-FET-e	V-MOS, 850V, 5A, 150W, <2,5Ω(5A)	18c$	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK794	MOS-N-FET-e	=2SK793: 900V	18c$	Tos	2SK727, 2SK1341, 2SK1649..50, 2SK1794,..
2SK795	MOS-N-FET-e	=2SK770: 15W	?30c$	Mat	-
2SK796	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 90W, <5Ω(5A)	16c($)	Mat	BUZ307, 2SK603, 2SK954, 2SK1339..
2SK796A	MOS-N-FET-e	=2SK796: 900V	16c($)	-	2SK696, 2SK726, 2SK1339
2SK797	MOS-N-FET-e	V-MOS, LogL, 60V, ±40A, 150W, <18mΩ(20A)	18c$	Nec	2SK1297, 2SK1514, 2SK1665
2SK798	MOS-N-FET-e	=2SK797: 100V, <31mΩ(20A)	18c$	Nec	2SK1263, 2SK1304
2SK799	MOS-N-FET-e	=2SK773: 450V <0,5Ω(5A)	16c$	Nec	BUK637-500, 2SK644, 2SK896, 2SK1488,..
2SK800	MOS-N-FET-e	=2SK774: 450V, <0,38Ω(5A)	16c$	Nec	2SK868A, 2SK870, 2SK1170, 2SK1518,..
2SK801(-Z)	MOS-N-FET-e	V-MOS, Sw, Pow, 30V, ±2A, 12W, <0,35Ω(5A)	30c$	Nec	2SK973..74, 2SK1763, 2SK1973
2SK802	MOS-N-FET-e	=2SK801: 15W	14b$	Nec	2SK1283
2SK803	MOS-N-FET-e	V-MOS, Sw, Pow, 160V, 8A, 40W, <0,38Ω	17c	Matsushita	BUK445-200, BUK545-200, 2SK1478
2SK804	MOS-N-FET-e	V-MOS, Sw, Pow, 150V, 20A, 100W, <0,12Ω	16c	Mat	2SK822, 2SK1549, 2SK2008
2SK805	MOS-N-FET-e	V-MOS, Sw, Pow, 200V, 20A, 100W, <0,19Ω	16c	Mat	2SK822, 2SK1549, 2SK2008
2SK806	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 3A, 50W, <2,7Ω(5A)	17c	Matsushita	2SK1572, 2SK1767, 2SK2144
2SK807	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 5A, 100W, <1,7Ω(5A)	16c	Mat	BUK427-600, 2SK1176, 2SK1463, 2SK1859
2SK808	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 1A, 45W, <7Ω(0,5A)	17c	Matsushita	BUK444-800, 2SK1142, 2SK1611, 2SK1834..
2SK808A	MOS-N-FET-e	=2SK808: 900V	17c	-	BUK446-1000, 2SK1174, 2SK1459, 2SK1994
2SK809	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 5A, 100W, <3Ω(5A)	16c	Mat	2SK1176, 2SK1463, 2SK1684, 2SK1859
2SK809A	MOS-N-FET-e	=2SK809: 900V	16c	-	2SK1176, 2SK1463, 2SK1684, 2SK1859
2SK810	MOS-N-FET-e	V-MOS, LogL, 100V, ±14A, 60W, <0,18Ω(5A)	17c$	Nec	2SK1301, 2SK1559, 2SK1561
2SK811	MOS-N-FET-e	=2SK810: Iso, ±12A, 35W	17c	Nec	BUK545-100, 2SK1035, 2SK1305
2SK812	MOS-N-FET-e	V-MOS, LogL, 60V, ±27A, 60W, <85mΩ(10A)	17c$	Nec	2SK1291, 2SK1296
2SK813	MOS-N-FET-e	=2SK810: Iso, ±21A, 35W	17c	Nec	2SK943, 2SK1214, 2SK1345..46
2SK814	MOS-N-FET-e	V-MOS, LogL, 30V, ±15A, 35W, <45mΩ(5A)	17c	Nec	2SK1034, 2SK1306, 2SK1558
2SK815	MOS-N-FET-e	V-MOS, LogL, 100V, ±21A, 35W, <85mΩ(10A)	17c	Nec	2SK1266, 2SK1307, 2SK1348..49
2SK817	MOS-N-FET-e	V-MOS, LogL, 50V, ±26A, 35W, <55mΩ(10A)	17c	Nec	2SK1262
2SK818	MOS-N-FET-e	V-MOS, Sw-Reg, 800V, 5A, 100W, <3Ω(5A)	18c$	Mat	2SK727, 2SK1649..50, 2SK1760, 2SK1794,..
2SK818A	MOS-N-FET-e	=2SK818: 900V	18c$	-	2SK727, 2SK1649..50, 2SK1760, 2SK1794,..
2SK819	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, ±10A, 100W, <1Ω(5A)	18c$	Nec	BUZ339, 2SK896, 2SK1488, 2SK1785..
2SK820	MOS-N-FET-e	V-MOS, 250V, n18A, 80W, <0,23Ω(10A)	18c	Nec	2SK901, 2SK944, 2SK1641, 2SK1673,..
2SK821	MOS-N-FET-e	V-MOS, 250V, ±20A, 150W, <0,23Ω(10A)	18c$	Nec	2SK901, 2SK944, 2SK1641, 2SK1673,..
2SK822	MOS-N-FET-e	V-MOS, 250V, ±22A, 90W, <0,15Ω(10A)	18c	Nec	2SK1670, (2SK944, 2SK1641, 2SK1673)
2SK823	MOS-N-FET-e	V-MOS, 250V, ±25A, 150W, <0,15Ω(10A)	18c$	Nec	2SK902, 2SK1669, 2SK1671, 2SK1675
2SK824	MOS-N-FET-e	V-MOS, 450V, ±12A, 90W, <0,5Ω(7,2A)	18c	Nec	2SK1268..69, 2SK1524, 2SK1831

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2SK825	MOS-N-FET-e	V-MOS, 450V, ±15A, 150W, <0,5Ω(7,2A)	18c$	Nec	BUZ338, 2SK899, 2SK1573, 2SK1610,..
2SK826	MOS-N-FET-e	V-MOS, 450V, ±15A, 95W, <0,38Ω(5A)	18c	Nec	2SK1268..69, 2SK1331, 2SK1524
2SK827	MOS-N-FET-e	V-MOS, 450V, ±18A, 150W, <0,38Ω(5A)	18c$	Nec	BUZ338, 2SK899, 2SK1610, 2SK1680,..
2SK828	MOS-N-FET-e	V-MOS, 500V, ±12A, 90W, <0,6Ω(7,2A)	18c	Nec	2SK1269, 2SK1331, 2SK1524
2SK829	MOS-N-FET-e	V-MOS, 500V, ±15A, 150W, <0,6Ω(7,2A)	18c$	Nec	BUZ338, 2SK899, 2SK1610, 2SK1757,..
2SK83	N-FET	FM/VHF, 25V, 10mA, 0.1W, Idss>0,5mA, Up<2,5V	7f	Mat,Mic	BF410A, 2SK193, 2SK195, 2SK606,..
2SK830	MOS-N-FET-e	V-MOS, 500V, ±15A, 95W, <0,45Ω(5A)	18c	Nec	2SK1269, 2SK1331, 2SK1524
2SK831	MOS-N-FET-e	V-MOS, 500V, ±18A, 150W, <0,45Ω(5A)	18c$	Nec	BUZ338, 2SK899, 2SK1500, 2SK1610,..
2SK832	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±4A, 85W, <4Ω(5A)	18c	Nec	2SK809A, 2SK1463
2SK833	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±5A, 150W, <4Ω(5A)	18c$	Nec	2SK727, 2SK794, 2SK1341, 2SK1794,..
2SK834	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±8A, 100W, <1,6Ω(5A)	18c	Nec	2SK1464, 2SK1685, 2SK1775
2SK839	MOS-N-FET	40V, 2A	-	Mat	-
2SK84	N-FET	AF/GenP, 55V, Idss=0,3..6,5mA, Up<5V	9e	Mat	BFS70, 2N3821, 2N4220, 2SK59, 2SK104,..
2SK840	MOS-N-FET	40V, 2A	-	Mat	-
2SK841	MOS-N-FET	250V, 1A	-	Mat	-
2SK842	MOS-N-FET	400V, 0,5A	-	Mat	-
2SK843	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, 10A, 40W, <0,1Ω(5A)	17c	Mitsubishi	BUK442-60, 2SK532, 2SK1093, 2SK1974..
2SK844	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 8A, 40W, <0,15Ω(5A)	17c	Mitsubishi	BUK443-100, BUZ72(A)F, 2SK1261
2SK845	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, 5A, 40W, <1,3Ω(5A)	17c	Mitsubishi	2SK1231..32, 2SK1351, 2SK1608, 2SK1626..
2SK846	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 45W, <4Ω(1,5A)	17c	Mitsubishi	2SK1356, 2SK1460
2SK847	MOS-N-FET-e	=2SK846: 120W	?18c	Mit	2SK726, 2SK1339
2SK848	MOS-N-FET-e	V-MOS, 250V, 0,5A, <9Ω(0,25A)	39b	Sanyo	-
2SK849	MOS-N-FET-e	V-MOS, 60V, 40A, 150W, <38mΩ(20A)	18c$	Tos	2SK1124, 2SK1514, 2SK1665
2SK85	GaAs-N-FET	UHF, 10V, 0,1A, 8GHz	52y*	Nec	-
2SK850	MOS-N-FET-e	V-MOS, 100V, 35A, 150W, <60mΩ(20A)	18c$	Tos	2SK1122, 2SK1263, 2SK1304
2SK851	MOS-N-FET-e	V-MOS, DC-DC, 200V, 30A, 150W, <85mΩ	18c$	Tos	BUZ341, 2SK1492, 2SK1669, 2SK1671,..
2SK852	N-FET	GenP, 50V, Idss=0,5..12mA, Up<1,5V	35f(2mm)	Nec	-
2SK852-X1	N-FET	-	35(2mm)	Nec	→2SK852
2SK852-X2	N-FET	-	35(2mm)	Nec	→2SK852
2SK852-X3	N-FET	-	35(2mm)	Nec	→2SK852
2SK852-X4	N-FET	-	35(2mm)	Nec	→2SK852
2SK853(A)	N-FET	GenP, 50V, Idss=0,5..12mA, Up<4,5V	35f(2mm)	Nec	-
2SK853A-K24	N-FET	-	35(2mm)	Nec	→2SK853A
2SK853A-K25	N-FET	-	35(2mm)	Nec	→2SK853A
2SK853A-K26	N-FET	-	35(2mm)	Nec	→2SK853A
2SK853A-K27	N-FET	-	35(2mm)	Nec	→2SK853A
2SK853-K4	N-FET	-	35(2mm)	Nec	→2SK853
2SK853-K5	N-FET	-	35(2mm)	Nec	→2SK853
2SK853-K6	N-FET	-	35(2mm)	Nec	→2SK853
2SK853-K7	N-FET	-	35(2mm)	Nec	→2SK853
2SK854	MOS-N-FET-e	V-MOS, 450V, ±5A, 50W, <1,4Ω(2,5A)	17c$	Nec	BUZ41A..42, BUZ90, 2SK893, 2SK1246,..
2SK855	MOS-N-FET-e	=2SK854: 500V, <1,5Ω(2,5A)	17c$	Nec	BUZ41A..42, BUZ90, 2SK893, 2SK1246
2SK856	MOS-N-FET-e	V-MOS, DC-DC, 60V, 45A, 125W, <0,03Ω	17c$	Tos	PRFZ42, 2SK1418, 2SK1542, 2SK1911
2SK857	MOS-N-FET-e	=2SK856:	18c$	Tos	2SK1124, 2SK1297, 2SK1665, 2SK2096,..
2SK858	MOS-N-FET-e	V-MOS, 600V, 2A, 40W, <4Ω(5A), 35/110nS	17c$	Tos	BUZ80, 2SK1323..24
2SK859	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 9A, 125W, <0,8Ω(5A)	18c$	Fjd	BUZ330, BUZ353, 2SK557, 2SK724..
2SK863	MOS-N-FET-e	?2SK1257	-	Mat	→2SK1257
2SK864	MOS-N-FET-e	?2SK1258	-	Mat	→2SK1258
2SK865	MOS-N-FET-e	?2SK1262	-	Mat	→2SK1262
2SK866	MOS-N-FET-e	?2SK1263	-	Mat	→2SK1263
2SK867	MOS-N-FET-e	V-MOS, Sw-Reg, 400V, 15A, 120W, <0,45Ω	18c$	Mat	BUK637-400, 2SK1610, 2SK1745, 2SK1757..
2SK867A	MOS-N-FET-e	=2SK867: 450V	18c$	-	BUK638-500, 2SK1610, 2SK1745, 2SK1757..
2SK868	MOS-N-FET-e	V-MOS, Sw, Pow, 400V, 20A, 130W, <0,35Ω	18c$	Mat	2SK1169..70, 2SK1517..18, 2SK1497..98,..
2SK868A	MOS-N-FET-e	=2SK868: 450V	18c$	-	2SK1169..70, 2SK1517..18, 2SK1497..98,..
2SK869	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 15A, 120W, <0,5Ω(5A)	18c$	Mat	BUZ338, 2SK1610, 2SK1745, 2SK1757,..
2SK87	N-FET	AF/GenP, 50V, Idss=0,3..6,5mA, Up<5V	2b	Hit	BFS70, 2N3821, 2N4220, 2SK59, 2SK104,..
2SK870	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 20A, 130W, <0,4Ω(10A)	18c$	Mat	2SK1170, 2SK1518, 2SK1498, 2SK1500..
2SK871	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±4A, 120W, <5,5Ω(5A)	18c$	Nec	2SK727, 2SK1461, 2SK1649..50, 2SK1760,..
2SK872	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±6A, 150W, <2,5Ω(5A)	18c$	Nec	2SK1358, 2SK1614, 2SK1692, 2SK1795..96..
2SK873	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, ±8A, 100W, <1,1Ω(5A)	18c$	Nec	BUZ330..331, BUZ385, 2SK1488
2SK874	MOS-N-FET-e	=2SK873: 500V, <1,2©(5A)	18c$	Nec	BUZ330..331, BUZ385, 2SK1488
2SK875	MOS-N-FET-e	V-MOS, Sw, Pow, 450V, ±12A, 120W, <0,6Ω(5A)	18c$	Nec	BUZ339, BUK637-500, 2SK724, 2SK896..
2SK876	MOS-N-FET-e	=2SK875: 500V, <0,7Ω(5A)	18c$	Nec	BUZ339, BUK637-500, 2SK724, 2SK896..
2SK879	N-FET	AF-Pre, 50V, Idss=0,3..6,5mA, Up<5V	35f(2mm)	Tos	-

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2SK879-GR	N-FET	-	35(2mm)	Tos	→2SK879
2SK879-O	N-FET	-	35(2mm)	Tos	→2SK879
2SK879-R	N-FET	-	35(2mm)	Tos	→2SK879
2SK879-Y	N-FET	-	35(2mm)	Tos	→2SK879
2SK880	N-FET	AF-Pre, 50V, Idss=0,6..14mA, Up<1,5V	35f(2mm)	Tos	-
2SK880-BL	N-FET	-	35(2mm)	Tos	→2SK880
2SK880-GR	N-FET	-	35(2mm)	Tos	→2SK880
2SK881	N-FET	FM/VHF, 18V, Idss=1..10mA, Up<4V	35c(2mm)	Tos	-
2SK881-GR	N-FET	-	35(2mm)	Tos	→2SK881
2SK881-O	N-FET	-	35(2mm)	Tos	→2SK881
2SK881-Y	N-FET	-	35(2mm)	Tos	→2SK881
2SK882	MOS-N-FET-d*	VHF, 20V, Idss=3..14mA, Up<2,5V	35c(2mm)	Tos	-
2SK882-GR	N-FET	-	35(2mm)	Tos	→2SK882
2SK888	MOS-N-FET-e	V-MOS, 100V, 15A, 75W, <0,18Ω(5A)	17c$	Tos	*IRF640..643, 2SK919, 2SK922, 2SK1301,..
2SK889	MOS-N-FET-e	V-MOS, 100V, 27A, 125W, <85mΩ(10A)	17c$	Tos	BUK456-100, 2SK1429
2SK890	MOS-N-FET-e	V-MOS, 200V, 10A, 75W, <0,4Ω(5A)	17c$	Tos	BUZ31..32, 2SK925, 2SK1221, 2SK1393
2SK891	MOS-N-FET-e	V-MOS, 200V, 18A, 125W, <0,18Ω(10A)	17c$	Tos	BUK456-200, BUZ30A, IRF640
2SK892	MOS-N-FET-e	V-MOS, 500V, 2,5A, 40W, <3Ω(5A)	17c$	Tos	BUZ74, IRF820, IRF822, 2SK858..
2SK893	MOS-N-FET-e	V-MOS, 500V, 5A, 75W, <1,5Ω(2,5A)	17c$	Tos	BUZ41A..42, IRF830, IRF832, 2SK1246..
2SK894	MOS-N-FET-e	V-MOS, 500V, 8A, 125W, <0,85Ω(5A)	17c$	Tos	BUK657-500, 2SK1496, 2SK1574
2SK895	MOS-N-FET-e	V-MOS, DC-DC, 450/20V, 12A, 125W, <0,6Ω	18c$	Tos	BUZ339, 2SK899, 2SK1515..16, 2SK1610,..
2SK896	MOS-N-FET-e	=2SK895: 500V	18c$	Tos	BUZ339, 2SK899, 2SK1516, 2SK1610..
2SK897	MOS-N-FET-e	V-MOS, Sw, Pow, 550V, 4A, 40W, <1,5Ω(2A)	?15c	Fjd	2SK1404, 2SK1637, 2SK2044, 2SK2118,+
2SK897-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 550V, 4A, 40W, <1,5Ω(2A)	17c	-	-
2SK899	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 18A, 125W, <0,33Ω(5A)	18c$	Fjd	2SK725, 2SK1170, 2SK1518, 2SK1680,..
2SK900	MOS-N-FET-e	V-MOS, Sw-Reg, 250V, 12A, 80W, <0,3Ω(5A)	17c$	Fjd	2SK925, 2SK1221, 2SK1393
2SK901	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 20A, 125W, <0,15Ω	18c$	Fjd	2SK623, 2SK944, 2SK1641, 2SK1673
2SK902	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 30A, 150W, <0,1Ω(10A)	18c$	Fjd	2SK1669, 2SK1671, 2SK1675..76
2SK903	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 40W, <4Ω(1,5A)	?15c	Fjd	2SK1356, 2SK1460, 2SK1995
2SK903-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 40W, <4Ω(1,5A)	17c	Fujitsu	2SK1356, 2SK1460, 2SK1995
2SK904	MOS-N-FET-e	=2SK903: 80W	17c$	Fjd	BUK456-800, 2SK791..792, 2SK1600..01
2SK905	MOS-N-FET-e	V-MOS, Sw, Pow, 50V, 45A, 125W, <0,03Ω	18c$	Fjd	BUZ347..348, 2SK857, 2SK1124, 2SK1514..
2SK906	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 32A, 125W, <0,06Ω	18c$	Fjd	BUZ341, 2SK850, 2SK1303, 2SK1429
2SK917	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 5A, 40W, <0,5Ω	17c$	Sanyo	IRF510, IRF512, 2SK357, 2SK628
2SK918	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 10A, 50W, <0,3Ω	17c$	Sanyo	BUZ20, BUZ72, 2SK740, 2SK1427
2SK919	MOS-N-FET-e	V-MOS, Sw, Pow, 100V, 15A, 60W, <0,15Ω	17c$	Sanyo	BUZ21, IRF530, 2SK888, 2SK1559
2SK92	N-FET	AF/HF-Pre, 20V, Idss=0,02..1mA, Up<0,8V	7e	Nec	2SK93, 2SK103
2SK920	MOS-N-FET-e	V-MOS, Sw, Pow, 120V, 5A, 40W, <0,6Ω	17c$	Sanyo	IRF620, 2SK357
2SK921	MOS-N-FET-e	V-MOS, Sw, Pow, 120V, 10A, 50W, <0,35Ω	17c$	Sanyo	BUZ31, 2SK740
2SK922	MOS-N-FET-e	V-MOS, Sw, Pow, 120V, 15A, 60W, <0,2Ω	17c$	Sanyo	IRF641, IRF643
2SK923	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 3A, 40W, <1,4Ω	17c$	Sanyo	BUZ76, 2SK310..311
2SK924	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 5A, 50W, <0,8Ω	17c$	Sanyo	BUZ60, 2SK358, 2SK1391
2SK925	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 10A, 60W, <0,45Ω	17c$	Sanyo	2SK926, 2SK1221, 2SK1393
2SK926	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, ±10A, 60W, <0,5Ω(5A)	17c$	Nec	2SK925, 2SK1221, 2SK1393
2SK928	MOS-N-FET-e	V-MOS, 450V, ±5A, 35W, <1,4Ω(2,5A)	17c	Nec	2SK1231..32, 2SK1351, 2SK1608, 2SK1626..
2SK929	MOS-N-FET-e	=2SK928: 500V, <1,5Ω(2,5A)	17c	Nec	2SK1232, 2SK1351, 2SK1608, 2SK1627,..
2SK93	N-FET	AF-Pre, 20V, Idss=18..564?A	7e	Son	2SK92, 2SK103
2SK930	N-FET	=2SK433:	35f(2mm)	Mit	-
2SK930-D	N-FET	-	35(2mm)	Mit	→2SK930
2SK930-E	N-FET	-	35(2mm)	Mit	→2SK930
2SK931	N-FET	GenP, 30V, Idss=5..30mA, Up<2V	35f	Sanyo	-
2SK931-21	N-FET	-	35	Sanyo	→2SK931
2SK931-22	N-FET	-	35	Sanyo	→2SK931
2SK931-23	N-FET	-	35	Sanyo	→2SK931
2SK931-24	N-FET	-	35	Sanyo	→2SK931
2SK931-25	N-FET	-	35	Sanyo	→2SK931
2SK932	N-FET	AM-Tuner, 15V, Idss=5..24mA, Up<1,4V	35f	Sanyo	2SK931
2SK932-21	N-FET	-	35	Sanyo	→2SK932
2SK932-22	N-FET	-	35	Sanyo	→2SK932
2SK932-23	N-FET	-	35	Sanyo	→2SK932
2SK932-24	N-FET	-	35	Sanyo	→2SK932
2SK933	MOS-N-FET-e	V-MOS, Sw, Pow, 60V, ±15A, 35W	17c	Sanyo	2SK1094, 2SK1286, 2SK1419
2SK934	MOS-N-FET-e	V-MOS, Sw, Pow, 250V, 8A, 40W, <0,52Ω(5A)	17c	Mitsubishi	2SK1478, 2SK1568..69, 2SK1668
2SK935	MOS-N-FET-e	=2SK934: 300V, <0,6Ω(5A)	17c	Mit	2SK1566, 2SK1569

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2SK936	MOS-N-FET-e	V-MOS, 50V, 30A, 45W, <0,03Ω(10A)	-	Sanyo	-
2SK937	N-FET	GenP, 40V, 0,1A, Idss=40..75mA, Up<5V	7e	Sanyo	-
2SK94	N-FET	50V, Idss=0,5..12mA, Up<1,5V	35f	Nec	2SK209, 2SK425
2SK940	MOS-N-FET-e*	V-MOS, LogL, 60V, 0,8A, 0,9W, <0,55Ω	7c(9mm)	Tos	2SK975, 2SK1274
2SK941	MOS-N-FET-e*	V-MOS, LogL, 100V, 0,6A, 0,9W, <1,3Ω	7c(9mm)	Tos	2SK1729, 2SK1736
2SK94-1	N-FET	-	35	Nec	→2SK94
2SK942	MOS-N-FET-e	V-MOS, LogL, 60V, 25A, 75W, <46mΩ(10A)	17c$	Tos	BUK555-60, 2SK972, 2SK1115, 2SK1296,..
2SK94-2	N-FET	-	35	Nec	→2SK94
2SK943	MOS-N-FET-e	=2SK942: Iso, 40W	17c	Tos	2SK1345, 2SK1214, 2SK1348..49, 2SK1897..
2SK94-3	N-FET	-	35	Nec	→2SK94
2SK944	MOS-N-FET-e	V-MOS, DC-DC, 250V, 22A, 150W, <0,15Ω	18c$	Tos	2SK901, 2SK1641, 2SK1673
2SK94-4	N-FET	-	35	Nec	→2SK94
2SK945	MOS-N-FET-e	V-MOS, DC-DC, 400V, 1A, 10W, <5Ω(0,5A)	30c$	Tos	2SK535, 2SK579..580, 2SK1151
2SK946	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, ±3A, 40W, <5,5Ω(5A)	17c	NEC	2SK1356, 2SK1460
2SK947	MOS-N-FET-e	V-MOS, Sw-Reg, 250V, 12A, 40W, <0,3Ω(6A)	?15c	Fjd	2SK526, 2SK1036, 2SK1762
2SK947-MR	MOS-N-FET-e	V-MOS, Sw-Reg, 250V, 12A, 40W, <0,3Ω(6A)	17c	Fujitsu	2SK526, 2SK1036, 2SK1762
2SK948	MOS-N-FET-e	=2SK947: 10W	30c$	Fjd	-
2SK949	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 6A, 40W, <1,2Ω(3,5A)	?15c	Fjd	2SK1232, 2SK1351, 2SK1608, 2SK1627, +
2SK949-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 6A, 40W, <1,2Ω(3,5A)	17c	Fujitsu	2SK1232, 2SK1351, 2SK1608, 2SK1627..
2SK95	N-FET	AF, Sw, 150V, Idss<28mA, Up<9V	-	Shi	-
2SK950	MOS-N-FET-e	=2SK949: 80W	17c$	Fjd	2SK893, 2SK1156, 2SK1246, 2SK1751,..
2SK951	MOS-N-FET-e	V-MOS, S-Reg, 800V, 2,5A, 40W, <7Ω(1A)	?15c	Fjd	BUK446-800, 2SK1142, 2SK1611, 2SK1834+
2SK951-MR	MOS-N-FET-e	V-MOS, Sw-Reg, 800V, 2,5A, 40W, <7Ω(1A)	17c	Fujitsu	BUK446-800, 2SK1142, 2SK1611, 2SK1834..
2SK952	MOS-N-FET-e	V-MOS, Sw-Reg, 800V, 2,5A, 40W, <7Ω(5A)	17c$	Fjd	BUZ80, 2SK1323..24, 2SK1456, 2SK1601,..
2SK953	MOS-N-FET-e	=2SK952: 80W	18c$	Fjd	BUZ307..308, 2SK954, 2SK1339
2SK954	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 3A, 100W, <4Ω(1,5A)	18c$	Fjd	BUZ307, 2SK538, 2SK603, 2SK1339
2SK955	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 5A, 125W, <2Ω(2,5A)	18c$	Fjd	2SK534, 2SK604, 2SK695, 2SK727, 2SK793
2SK956	MOS-N-FET-e	V-MOS, Sw, Pow, 800V, 9A, 150W, <1,5Ω(5A)	18c$	Fjd	2SK1032, 2SK1796
2SK957	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 2A, 40W, <8,5e(1A)	?15c	Fjd	2SK1143, 2SK1275, 2SK1459
2SK957-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 2A, 40W, <8,5Ω(1A)	17c	Fujitsu	2SK1143, 2SK1275, 2SK1459
2SK958	MOS-N-FET-e	=2SK957: 45W	17c$	Fjd	2SK1199, 2SK1338, 2SK1324
2SK959	MOS-N-FET-e	=2SK957: 80W	18c$	Fjd	2SK726, 2SK1339
2SK96	N-FET	=2SK95: 200V	-	Shi	-
2SK960	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 40W, <5e(1,5A)	?15c	Fjd	2SK1356, 2SK1460, 2SK1995
2SK960-MR	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 3A, 40W, <5Ω(1,5A)	17c	Fujitsu	2SK1356, 2SK1460, 2SK1995
2SK961	MOS-N-FET-e	=2SK960: 80W	17c$	Fjd	2SK1601, 2SK1456, 2SK1638, 2SK1793,..
2SK962(-01)	MOS-N-FET-e	V-MOS, Sw, Pow, 900V, 8A, 150W, <2Ω(5A)	18c$	Fjd	2SK1358, 2SK1614, 2SK1502, 2SK1795..
2SK963	MOS-N-FET-e	=2SK758: 15W	?30c$	Mat	-
2SK968	N-FET	FM, 20V, Idss=0,6..12mA, Up<2,5V	35c	Sanyo	2SK608
2SK968-2	N-FET	-	35	Sanyo	→2SK968
2SK968-3	N-FET	-	35	Sanyo	→2SK968
2SK968-4	N-FET	-	35	Sanyo	→2SK968
2SK968-5	N-FET	-	35	Sanyo	→2SK968
2SK969	GaAs-N-FET	HF, 16V, 20mA, Idss=1,2..12mA	35c	Sanyo	-
2SK97	N-FET	Dual, 30V, Idss=0,9..14,3mA, Up<1,49V	6-DIP/bo	Son	-
2SK970	MOS-N-FET-e*	V-MOS, LogL, 60V, 10A, 30W, <0,15Ω(5A)	17c$	Hit	2SK1114, 2SK1300
2SK971	MOS-N-FET-e*	V-MOS, LogL, 60V, 15A, 40W, <65mΩ(5A)	17c$	Hit	BUK552-60, 2SK942, 2SK1115..16, 2SK1347
2SK972	MOS-N-FET-e*	V-MOS, LogL, 60V, 25A, 50W, <40mΩ(10A)	17c$	Hit	BUK555-60, 2SK942, 2SK1115, 2SK1296,..
2SK973(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 2A, 10W, <0,35Ω(5A)	30c$	Hit	2SK1763
2SK974(L,S)	MOS-N-FET-e*	V-MOS, LogL, 60V, 3A, 20W, <0,18Ω(5A)	30c$	Hit	2SK1113, 2SK1254, 2SK1282
2SK975	MOS-N-FET-e*	V-MOS, LogL, 60V, 1,5A, 0,9W, <0,4Ω(5A)	7c,b(9mm)	Hit	2SK1274, 2SK1733
2SK976	MOS-N-FET-e*	=2SK970: Iso, 20W	17c	Hit	2SK1093, 2SK1895, 2SK1878
2SK977	MOS-N-FET-e*	=2SK971: Iso, 25W	17c	Hit	2SK1094, 2SK1286, 2SK1306
2SK978	MOS-N-FET-e*	=2SK972: Iso, 30W	17c	Hit	2SK1290, 2SK1897, 2SK1951
2SK979	MOS-N-FET-e	V-MOS, 450V, 10A, 120W, 0,5Ω(5A)	18c$	Sak	2SK724, 2SK896, 2SK1488, 2SK1752,..
2SK980	N-FET	Video-Freq., 12V, 40mA, Idss>8mA	35f	Hit	-
2SK980-F	N-FET	-	35	Hit	→2SK980
2SK980-G	N-FET	-	35	Hit	→2SK980
2SK981(A)	MOS-N-FET-e	=2SK762(A): 15W	?30c$	Mat	-
2SK982	MOS-N-FET-e	Sw, 60V, 0,2A, 0,4W, <1Ω(50(A), 14/75nS	7c	Tos	BS170, BST170, 2SK422..423
2SK984	GaAs-N-FET	SHF, C..K-Band, 4V, Idss=0,5..2mA	52y	Nec	-
2SK987	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 5A, 40W, <1,6Ω(5A)	17c	Mitsubishi	2SK1232, 2SK1351, 2SK1608, 2SK1627..
2SK988	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 45W, <0,9©(5A)	17c	Mitsubishi	-
2SK989	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 10A, 120W, <0,9Ω(5A)	?18c$	Mit	2SK896, 2SK1488, 2SK1753, 2SK1785,..

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2SK990	MOS-N-FET-e	V-MOS, Sw, Pow, 500V, 15A, 150W, <0,65Ω(5A)	?18c$	Mit	2SK899, 2SK1610, 2SK1678, 2SK1745,..
2SK991	MOS-N-FET-e*	V-MOS, LogL, 100V, ±4A, 35W, <0,5Ω(5A)	17c$	Nec	BUK552-100, IRL510(A)
2SK992	MOS-N-FET-e*	=2SK991: Iso, 30W	17c	Nec	BUK542-100, 2SK1260, 2SK1265
2SK993	MOS-N-FET-e*	V-MOS, LogL, 60V, ±8A, 35W, <0,25Ω(5A)	17c$	Nec	BUK552-100
2SK994	MOS-N-FET-e*	=2SK993: Iso, ±7A, 30W	17c	Nec	BUK542-60, 2SK1033, 2SK1256, 2SK1344,..
2SK995	MOS-N-FET-e	FREDFET, Sw-Pow, 550V, 5A, 60W, <1,8Ω(5A)	16c	Mat	BUK627-600
2SK996	MOS-N-FET-e	V-MOS, Sw, Pow, 600V, 4A, 50W, <1,8Ω(5A)	17c	Matsushita	2SK1118, 2SK1404, 2SK1637, 2SK2044,..
2SK997	N-FET	Cond-Microphone-Preamp, 20V, 10mA, Idss>0,1mA	40a	Nec	-
2SK998	N-FET	UHF, 20V, 35mA, Idss>8mA, Up<2,2V	7d	Nec	-
2SM148	Triac	200V, 6A(Tc=75°), Igt/Ih<45/10mA	22a$	Sanyo	T2700B, TAG261-200, TAG266-200,..
2SM149	Triac	=2SM148: 400V	22a$	Sanyo	T2700D, TAG261-400, TAG266-400...
2SM150	Triac	=2SM148: 600V	22a$	Sanyo	T2700M, TAG261-600, TAG266-600,..
2SM152	Triac	200V, 1A, Igt<15mA	13h$	Matsushita	TAG137..TAG138..
2ST1396	Si-NPN+Diode	=2SD1396	18j$	STE	→2SD1396
2ST1651FI	Si-NPN+Diode	=2SD1651	18c	STE	→2SD1651
2ST1877FI	Si-NPN+Diode	=2SD1877	18c	STE	→2SD1877
2ST1942	Si-NPN	=2SC1942	23a$	STE	→2SC1942
2ST2000	Si-NPN	=S2000	18j$	STE	→S2000
2ST2000FI	Si-NPN	=S2000AF	18c	-	→S2000AF
2ST3153	Si-NPN	=2SC3153: 1000V	18j$	STE	→2SC3153
2ST3412	Si-NPN	=2SC3412	23a$	STE	→2SC3412
2ST3460	Si-NPN	=2SC3460: 1500V	18j$	STE	BU508A, BU908, BU2508A
2ST3461	Si-NPN	=2SC3461: 1500V	18j$	STE	BU508A, BU908, BU2508A
2ST3485	Si-NPN	=2SC3485	18j$	STE	→2SC3485
2ST3485FI	Si-NPN	=2SC3485: Iso	18c	STE	2SC3884A, 2SC3894
2ST3552	Si-NPN	=2SC3552: 1200V	18j$	STE	→2SC3552
2ST3642	Si-NPN	=2SC3642: 1200V	18j$	STE	→2SC3642
2ST3679FI	Si-NPN	=2SC3679: Iso, 1000V	18c	STE	BUW11AF, 2SC4300, 2SC4427
-2T	Si-P	=PMST4403 (Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST4403
2T201	Ge-PNP	→2SA121..123	-	Son	-
2T301	Ge-PNP	→2SB140	-	Son	-
2T302	Ge-PNP	→2SB141	-	Son	-
2T303	Ge-PNP	→2SB142..144	-	Son	-
2T304	Ge-PNP	→2SB145..146	-	Son	-
2T305	Ge-PNP	→2SB27..29	-	Son	-
2T306	Ge-PNP	→2SB30..31	-	Son	-
2T31	Ge-PNP	→2SB48..50	-	Son	-
2T32	Ge-PNP	→2SB51..52	-	Son	-
2T38	Ge-PNP	→2SB53	-	Son	-
2T73	Ge-NPN	→2SC73	-	Son	-
2T75	Ge-NPN	→2SC75	-	Son	-
2T76	Ge-NPN	→2SC76	-	Son	-
2T77	Ge-NPN	→2SC77	-	Son	-
2T78	Ge-NPN	→2SC78	-	Son	-
2V435	Si-PNP	→2N3726	-	Sgs	-
2W01M..10M	Si-Br	50..1000V, 2A	8	-	B30..500C2200
-2X	Si-N	=PMST4401 (Typ-Code/Stempel/marking)	35(2mm)	Phi	→PMST4401
2Z12..51	Z-Di/TVS	TAZ, 12..51V, 10%, 600W(1µS)	31a	Tos	BZW70/..BZX70/..BZY93/..
3					
-30	Si-N+R	=PDTC114YU (Typ-Code/Stempel/marking)	35(2mm)	Phi	→PDTC114YU
30D1..D4	Si-Di	-	31a	IRF	BY251..255, GP30A..M, 1N5400..08, +
30DF1..DF6	Si-Di	-	31a	Inr, Fag	BYW95A..C, BYW96D..E, RG3A..M, +
30DL1..DL4	Si-Di	-	31a	IRF	BYW95A..C, BYW96D..E, RG3A..M, +
30FWJ2C48M	Si-Di	-	30p	Toshiba	U30FWJ2C48M
30FWJ2CZ47M	Si-Di	-	17p	Toshiba	MBRF2545CT
30GWJ2C42C	Si-Di	-	18p	Toshiba	BY528-45, BYV73-40, MBR3045PT
30GWJ2C48C	Si-Di	-	30p	Toshiba	U30GWJ2C48C
30GWJ2CZ47C	Si-Di	-	17p	Toshiba	MBRF2545CT
30JL2C41	Si-Di	-	18p$	Toshiba	MUR3060PT
31DF1..DF6	Si-Di	-	31a	IRF	BYW178, EGP30D..G, FE3D..H
359V	Si-Di	-	31a	Mic	BY227, BYX86, GP15M, 1N5399..
35SP-01..10	Si-Di	-	?70	Gie	-
37740	Si-PNP	?BC214	2a	Rca	→BC214

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37741	Si-NPN	?2N5320	2a	Rca	→2N5320
38387	Si-NPN	=40361	2a$	Rca	→40361
38388	Si-PNP	=40362	2a$	Rca	→40362
384P	Si-Di	-	31a	Mic	BY227,BY255,BYWS6,GP15M..
384V	Si-Di	-	31a	-	BY227,BY255,BYX87,GH3E..
385A	Si-Di	-	31a	Mic	BY231/800,BY245/800,MR810..818..
385B	Si-Di	-	31a	-	BY231/800,BY245/800,MR811..818..
385C	Si-Di	-	31a	-	BY231/800,BY245/800,MR812..818..
385D	Si-Di	-	31a	-	BY231/800,BY245/800,MR812..818..
385F	Si-Di	-	31a	-	BY231/800,BY245/800,MR813..818..
385H	Si-Di	-	31a	-	BY231/800,BY245/800,MR814..818..
385K	Si-Di	-	31a	-	BY231/800,BY245/800,MR816..818..
385M	Si-Di	-	31a	-	BY231/800,BY245/800,MR816..818..
38647	Si-NPN	?2N5320	2a	Rca	→2N5320
386A	Si-Di	-	31a	Mic	BY201/2,BYT52A,BYV12,RGP10A..
386B	Si-Di	-	31a	-	BY201/2,BYT52B,BYV12,RGP10B..
386C	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
386D	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
386F	Si-Di	-	31a	-	BY201/3,BYT52G,BYV13,RGP10G..
386H	Si-Di	-	31a	-	BY201/4,BYT52G,BYV13,RGP10G..
386K	Si-Di	-	31a	-	BY201/5,BYT52J,BYV14,RGP10J..
386M	Si-Di	-	31a	-	BY201/6,BYT52J,BYV14,RGP10J..
387A	Si-Di	-	31a	Mic	BY201/2,BYT52A,BYV12,RGP10A..
387B	Si-Di	-	31a	-	BY201/2,BYT52B,BYV12,RGP10B..
387C	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
387D	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
387F	Si-Di	-	31a	-	BY201/3,BYT52G,BYV13,RGP10G..
387H	Si-Di	-	31a	-	BY201/4,BYT52G,BYV13,RGP10G..
387K	Si-Di	-	31a	-	BY201/5,BYT52J,BYV14,RGP10J..
387M	Si-Di	-	31a	-	BY201/6,BYT52J,BYV14,RGP10J..
388A	Si-Di	-	31a	Mic	BY201/2,BYT52A,BYV12,RGP10A..
388B	Si-Di	-	31a	-	BY201/2,BYT52B,BYV12,RGP10B..
388C	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
388D	Si-Di	-	31a	-	BY201/2,BYT52D,BYV13,RGP10D..
388F	Si-Di	-	31a	-	BY201/3,BYT52G,BYV13,RGP10G..
388H	Si-Di	-	31a	-	BY201/4,BYT52G,BYV13,RGP10G..
388K	Si-Di	-	31a	-	BY201/5,BYT52J,BYV14,RGP10J..
388M	Si-Di	-	31a	-	BY201/6,BYT52J,BYV14,RGP10J..
398P	Si-Di	-	31a	Mic	BY254..255,BYW17/800,BYW85..
398V	Si-Di	-	31a	-	BY255,BYW17/1000,BYW86..
3A16	N-FET	?2N3819	7e	-	→2N3819
3AA11	Si-P-Darl+Di	3xDarl,-/100V,2A,2W,B>1000	8-SIP	Rhm	-
3AA12	Si-P-Darl+Di	3xDarl,-/120V,6A,2W,B>2000	8-SIP	Rhm	-
3AA13	Si-P-Darl+Di	3xDarl,-/80V,4A,2W,B>1000	8-SIP	Rhm	-
3AC11	Si-N-Darl+Di	3xDarl,-/100V,2A,2W,B>1000	8-SIP	Rhm	-
3AC12	Si-N-Darl+Di	3xDarl,-/120V,6A,2W,B>2000	8-SIP	Rhm	-
3AC13	Si-N-Darl+Di	3xDarl,-/80V,4A,2W,B>1000	8-SIP	Rhm	-
3C2	N-FET	?2N5245	7e	-	→2N5245
3C2P	N-FET	?2N5245	7f	-	→2N5245
3EZ3.9..200D	Z-Di	3,9..200V,3W	31a	Mot,Sie	BZT03/..BZV16/..BZX40/..BZV48/..
3GWJ2C42	Si-Di	-	30p	Toshiba	U3GWJ2C42
3JU41	Si-Di	-	31a	Toshiba	BYM36C,BYTS6J,BYV28/600
3LN01C	MOS-N-FET-e*	V-MOS,LogL,30V,0,15A,<3,7Ω	35a	Sanyo	2SK1582,2SK2731,2SK1590..91
3LN01M	MOS-N-FET-e*	V-MOS,LogL,30V,0,15A,<5,2Ω	35a(2mm)	Sanyo	-
3LN02M	MOS-N-FET-e*	V-MOS,LogL,30V,0,3A,<1,2Ω	35a(2mm)	Sanyo	-
3LP02C	MOS-P-FET-e*	V-MOS,LogL,30V,0,2A,<4,9Ω	35a	Sanyo	BSH201
3LP02M	MOS-P-FET-e*	V-MOS,LogL,30V,0,2A,<3,1Ω	35a(2mm)	Sanyo	-
3N100	Si-PNP	Chopper,20V,50mA,0,3W	5z$	Tdy	-
3N101	Si-PNP	Chopper,30V,50mA,0,3W	5z$	Tdy	-
3N102	Si-PNP	Chopper,40V,50mA,0,3W	5z$	Tdy	-
3N103	Si-PNP	Chopper,50V,50mA,0,3W	5z$	Tdy	-
3N104	Si-PNP	Chopper,60V,50mA,0,3W	5z$	Tdy	-
3N105	Si-PNP	Chopper,20V,50mA,0,3W	5z$	Tdy	-
3N106	Si-PNP	Chopper,40V,50mA,0,3W	5z$	Tdy	-

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3N107	Si-PNP	Chopper, 60V, 50mA, 0,3W	5z$	Tdy	-
3N108	Si-PNP	Chopper, 50V, 20mA, 0,3W	5z$	Tdy,Tix	-
3N109	Si-PNP	Chopper, 50V, 20mA, 0,3W	5z$	Tdy	-
3N110	Si-PNP	Chopper, 50V, 20mA, 0,3W	5z$	Tdy	-
3N111	Si-PNP	Chopper, 50V, 20mA, 0,3W	5z$	Tdy	-
3N112	Si-PNP	Chopper, 50V, 20mA, 0,2W	-	Tra	-
3N113	Si-PNP	Chopper, 50V, 20mA, 0,2W	-	Spr,Tdy,Tra	-
3N114	Si-PNP	Chopper, 30V, 20mA, 0,3W	5y$	Tdy	-
3N115	Si-PNP	Chopper, 30V, 20mA, 0,3W	5y$	Tdy	-
3N116	Si-PNP	Chopper, 30V, 20mA, 0,3W	5y$	Tdy	-
3N117	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N118	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N119	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N120	Si-NPN	Chopper, 30V, 10mA, 0,2W	5y$	Sld,Tdy	-
3N121	Si-NPN	Chopper, 30V, 10mA, 0,2W	5y$	Sld,Tdy	-
3N123	Si-PNP	Chopper, 30V, 20mA, 0,1W	5y$	Tdy	-
3N124	N-FET	Dual-Gate, 50V, Idss>0,2mA, Up<8V	5r=+	Mot	-
3N125	N-FET	=3N124: Idss>1,5mA, Up<14V	5r=+	Mot	-
3N126	N-FET	=3N124: Idss>3mA, Up<26V	5r=+	Mot	-
3N127	Si-NPN	Chopper, 30V, 10mA, 0,2W	5z$	Tra	-
3N128	MOS-N-FET-d	VHF-Pre/Osc, 20V, Idss>5mA, Up<8V	5m+	MOT,Rca,++	BFR29,3N143,3N152,3N154
3N129	Si-PNP	Chopper, 20V, 20mA, 0,3W	5z$	Tdy	-
3N130	Si-PNP	Chopper, 30V, 20mA, 0,3W	5z$	Tdy	-
3N131	Si-PNP	Chopper, 40V, 20mA, 0,3W	5z$	Tdy	-
3N132	Si-PNP	Chopper, 50V, 20mA, 0,3W	5z$	Tdy	-
3N133	Si-PNP	Chopper, 60V, 20mA, 0,3W	5z$	Tdy	-
3N134	Si-PNP	Chopper, 20V, 20mA, 0,3W	5z$	Tdy	-
3N135	Si-PNP	Chopper, 40V, 20mA, 0,3W	5z$	Tdy	-
3N136	Si-PNP	Chopper, 60V, 20mA, 0,3W	5z$	Tdy	-
3N138	MOS-N-FET-d	Sw, Chopper, 45V, 0,05A	5m+	Gie,Rca	-
3N139	MOS-N-FET-d	AF, VHF, 42V, Idss>5mA	5m+	Gie,Rca	-
3N140	MOS-N-FET-d	Dual-Gate, FM/VHF-Pre, 20V, Idss>5mA	5t*+	Gie,Mot,Rca	BF351,3N201..206,3N211..213
3N141	MOS-N-FET-d	Dual-Gate, FM/VHF-Mix, 20V, Idss>5mA	5t*+	Gie,Rca	BF351,3N201..206,3N211..213
3N142	MOS-N-FET-d	FM/VHF-Pre/Mix/Osc, 20V, Idss>5mA, Up<8V	5m+	Gie,Rca	BFR29,3N143,3N152,3N154
3N143	MOS-N-FET-d	VHF-Mix/Osc, 20V, IµS>10mA, Up<8V	5m+	Gie,Rca	BFR29,3N142,3N152,3N154
3N145	MOS-P-FET-e	GenP, Chopper, 30V, Up<6V	5n+	Gie	-
3N146	MOS-P-FET-e	GenP, Chopper, 30V, Up<6V	5n+	Gie	-
3N147	MOS-P-FET-e	Dual, 20V, Idss>8mA, Up<12V	81bz	Gie	-
3N148	MOS-P-FET-e	Dual, 20V, Idss>8mA, Up<12V	81bz	Gie	-
3N149	MOS-P-FET-e	GenP, Chopper, 30V, Idss>16mA, Up<6V	5n+	Gie	-
3N150	MOS-P-FET-e	GenP, Chopper, 30V, Idss>16mA, Up<6V	5n+	Gie	-
3N151	MOS-P-FET-e	Dual, 30V, Idss<3mA, Up<6V	81bw	Gie	-
3N152	MOS-N-FET-d	VHF, LN, 20V, Idss>10mA, Up<8V	5m+	Gie,Rca	BFR29,3N143,3N154
3N153	MOS-N-FET-d	Chopper, 20V, 0,05A	5m+	Gie,Rca	-
3N154	MOS-N-FET-d	VHF-Pre, 20V, Idss>10mA, Up<8V	5m+	Gie,Rca	BFR29,3N143,3N152
3N155(A)	MOS-P-FET-e	Chopper, 35V, 0,03A, Up<3,2V	5g+	Gie,Mot,Tix	BFW27,3N160..161,3N163..164
3N156(A)	MOS-P-FET-e	=3N155: Up<5V	5g+	Gie,Mot,Tix	BFW27,3N160..161,3N163..164
3N157(A)	MOS-P-FET-e	Chopper, 35..50V, 0,03A, Up<3,2V	5g+	Gie,Mot,Tix	BFW27,3N160..161,3N163..164
3N158(A)	MOS-P-FET-e	=3N157: Up<5V	5g+	Gie,Mot,Tix	BFW27,3N160..161,3N163..164
3N159	MOS-N-FET-d	Dual-Gate, 20V, Idss>5mA, Up<4V	5t*+	Gie,Rca	BF351,3N201..206,3N211..213
3N160	MOS-P-FET-e	Chopper, 25V, 0,125A, Up<5V	5n+	Gie,Isi,Tix	-
3N161	MOS-P-FET-e*	Chopper, 25V, 0,125A, Up<5V	5n+	Gie,Isi,Tix	-
3N162	MOS-P-FET-e	Chopper, 25V, 0,25A, Up<5V	5n+	Gie	-
3N163	MOS-P-FET-e	Chopper, 40V, 0,05A, Up<5V	5n+	Six,Tix,++	-
3N164	MOS-P-FET-e	Chopper, 30V, 0,05A, Up<5V	5n+	Six,Tix,++	-
3N165	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	81bz+	Gie,Isi,++	-
3N166	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	81bz+	Gie,Isi,++	-
3N167	MOS-P-FET-e	Chopper, 30V, 0,5A, Up<6V	5n+	Gie	-
3N168	MOS-P-FET-e	Chopper, 25V, 0,5A, Up<6V	5n+	Gie	-
3N169	MOS-N-FET-e	Sw, 35V, 0,03A, Up<1,5V	5g+	Mot,Tix,++	-
3N170	MOS-N-FET-e	=3N169: Up<2	5g+	Mot,Tix,++	-
3N171	MOS-N-FET-e	=3N169: Up<3	5g+	Mot,Tix,++	-
3N172	MOS-P-FET-e*	Chopper, 40V, 0,05A, Up<6V	5n+	Gie,Isi,Sol	-
3N173	MOS-P-FET-e*	=3N172: 30V	5n+	Gie,Isi,Sol	-

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3N174	MOS-P-FET-e	Chopper, 30V, 0,02A, Up<6V	5n+	Gie,Tix	BFW27, 3N155..158, 3N163..164
3N175	MOS-N-FET-e	Chopper, 30V, 0,05A, Up<2V	5g+	Gie	-
3N176	MOS-N-FET-e	Chopper, 25V, 0,05A, Up<2,5V	5g+	Gie	-
3N177	MOS-N-FET-e	Chopper, 20V, 0,05A, Up<3,5V	5g+	Gie	-
3N178	MOS-P-FET-e	Chopper, 75V, 0,02A, Up<S,5V	5n+	Gie	-
3N179	MOS-P-FET-e	Chopper, 60V, 0,02A, Up<6V	5n+	Gie	-
3N180	MOS-P-FET-e	Chopper, 40V, 0,02A, Up<6V	5n+	Gie	-
3N181	MOS-P-FET-e	Chopper, 30V, 0,1A, Up<4V	5n+	Gie	-
3N182	MOS-P-FET-e	Chopper, 30V, 0,1A, Up<5V	5n+	Gie	-
3N183	MOS-P-FET-e	Chopper, 25V, 0,1A, Up<6V	5n+	Gie	-
3N184	MOS-P-FET-e	Chopper, 35V, 0,05A, Up<3V	5n+	Gie	-
3N185	MOS-P-FET-e	Chopper, 30V, 0,05A, Up<3V	5n+	Gie	-
3N186	MOS-P-FET-e	Chopper, 25V, 0,05A, Up<3,5V	5n+	Gie	-
3N187	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss>5mA, Up<4V	5t*+	Gie,Rca,Sol	BF351, 3N201..206, 3N211..213
3N188	MOS-P-FET-e*	Dual, Chopper, 40V, 0,05A, Up<5V	81bw+	Gie,Isi,Sol	-
3N189	MOS-P-FET-e*	Dual, Chopper, 40V, 0,05A, Up<5V	81bw+	Gie,Isi,Sol	-
3N190	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	81bw+	Gie,Isi,Sol	-
3N191	MOS-P-FET-e	Dual, Chopper, 40V, 0,05A, Up<5V	81bw+	Gie,Isi,Sol	-
3N192	MOS-N-FET-d	VHF, 30V, Idss<30mA, Up<4V	5m+	Gie	-
3N193	MOS-N-FET-d	=3N192: Idss<20mA	5m+	Gie	-
3N200	MOS-N-FET-d*	Dual-Gate, VHF/UHF, 20V, Idss>0,5mA	5t*+	Gie,Rca	3SK66, 3SK79, 3SK87, 3SK100
3N201	MOS-N-FET-d*	Dual-Gate, VHF-Amp, 30V, Idss>6mA, Up<5V	5t*+	Gie,Mot,Tix	BF351, 3N209..213
3N202	MOS-N-FET-d*	Dual-Gate, VHF-Mix, 30V, Idss>6mA, Up<5V	5t*+	Gie,Mot,Tix	BF351, 2N209..213
3N203(A)	MOS-N-FET-d*	Dual-Gate, TV-IF, 30V, Idss>3mA, Up<5V	5t*+	Gie,Mot,Tix	BF351, 3N209..213
3N204	MOS-N-FET-d*	Dual-Gate, VHF/UHF, 30V, Idss>6mA	5t*+	Gie,Mot,Tix	3N209..210
3N205	MOS-N-FET-d*	Dual-Gate, VHF-Mix, 30V, Idss>6mA, Up<5V	5t*+	Gie,Mot,Tix	BF351, 3N209..213
3N206	MOS-N-FET-d*	Dual-Gate, TV-IF, 30V, Idss>3mA, Up<5V	5t*+	Gie,Mot,Tix	BF351, 3N209..213
3N207	MOS-P-FET-e	Dual, 25V, 0,1A, Up<6V	81bw*	Gie,Tix	MEM551
3N208	MOS-P-FET-e*	Dual, 25V, 0,1A, Up<6V	81bw*	Gie,Tix	MEM550
3N209	MOS-N-FET-d*	Dual-Gate, UHF, 30V, Idss>5mA, Up<4V	5t*+	Mot	(BF900)
3N21	Ge-PNP	Tetrode, 60V, 0,1W	-	Syl	-
3N210	MOS-N-FET-d*	Dual-Gate, UHF, 30V, Idss>5mA, Up<4V	-	Mot	(BF900)
3N211	MOS-N-FET-d*	Dual-Gate, VHF-Amp, 35V, Idss>6mA, Up<5V	5t*+	Mot,Rca,Tix	BF351, 3N201..206
3N212	MOS-N-FET-d*	=3N211: VHF-M, Up<4V	5t*+	Mot,Rca,Tix	BF351, 3N201..206
3N213	MOS-N-FET-d*	=3N211: TV-IF, 40V	5t*+	Mot,Rca,Tix	BF351, 3N201..206
3N214	MOS-N-FET-d	GenP, 20V, Idss>50mA, Up<6V	5m+	Gie,Tix	-
3N215	MOS-N-FET-d	GenP, 20V, Idss>50mA, Up<6V	5m+	Gie,Tix	-
3N216	MOS-N-FET-d	GenP, 20V, Idss>50mA, Up<6V	5m+	Gie,Tix	-
3N217	MOS-N-FET-d	GenP, 20V, Idss>50mA, Up<6V	5m+	Gie,Tix	-
3N218	MOS-P-FET-e	Chopper, 25V, 0,7A, Up<3,5V	5n+	Gie	-
3N22	Ge-NPN	Tetrode, 15V, 0,03W	-	Wes	-
3N223	MOS-N-FET-d	Dual-Gate, VHF, 40V, Idss<12mA, Up<2V	5t*+	Mot	BF352..353, BF963, 3SK81
3N224	MOS-N-FET-d	Dual-Gate, VHF, 40V, Idss<12mA, Up<2V	-	Mot	BF352..353, BF963, 3SK81
3N225(A)	MOS-N-FET-d	Dual-Gate, UHF, 25V, Idss>1mA, Up<4V	5t*+	TI	3SK70, 3SK80
3N23	Ge-NPN	Tetrode, 30V, 5mA, 0,05W	-	Gie	-
3N242	MOS-N-FET-e	Chopper, 30V, 0,03A, Up<2V	5g+	Gie	-
3N246	Si-Br	Rect-Br, 50V, 1A	33	Gie	B35C1000, etc.
3N247	Si-Br	=3N246: 100V	33	-	B70C1000, etc.
3N248	Si-Br	=3N246: 200V	33	-	B140C1000, etc.
3N249	Si-Br	=3N246: 400V	33	-	B280C1000, etc.
3N25	Ge-PNP	Tetrode, 15V, 2mA, 0,025W	-	TI	-
3N250	Si-Br	=3N246: 600V	33	-	B420C1000, etc.
3N251	Si-Br	=3N246: 800V	33	-	B560C1000, etc.
3N252	Si-Br	=3N246: 1000V	33	-	B700C1000, etc.
3N253	Si-Br	Rect-Br, 50V, 2A	33	Mot	B35C2000, etc.
3N254	Si-Br	=3N253: 100V	33	-	B70C2000, etc.
3N255	Si-Br	=3N253: 200V	33	-	B140C2000, etc.
3N256	Si-Br	=3N253: 400V	33	-	B280C2000, etc.
3N257	Si-Br	=3N253: 600V	33	-	B420C2000, etc.
3N258	Si-Br	=3N253: 800V	33	-	B560C2000, etc.
3N259	Si-Br	=3N253: 1000V	33	-	B700C2000, etc.
3N26	Si-NPN	Tetrode, 30V, 10mA, 0,125W	-	TI	-
3N27	Si-NPN	Tetrode, 30V, 10mA, 0,125W	-	TI	-
3N29	Ge-NPN	Tetrode, 7V, 20mA, 0,05W	-	Gen	-

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3N30	Ge-NPN	Tetrode, 7V, 20mA, 0,05W	-	Gen	-
3N31	Ge-NPN	Tetrode, 7V, 20mA, 0,05W	-	Gen	-
3N32	Si-NPN	Tetrode, 30V, 10mA, 0,125W	-	TI	-
3N33	Si-NPN	Tetrode, 30V, 10mA, 0,125W	-	TI	-
3N34	Si-NPN	Tetrode, 30V, 20mA, 0,125W	5	TI	-
3N35(A)	Si-NPN	Tetrode, 30V, 20mA, 0,125W	5	Tdy,Tix	-
3N36	Ge-NPN	Tetrode, 7V, 20mA, 0,03W	5	Gen	-
3N37	Ge-NPN	Tetrode, 7V, 20mA, 0,03W	5	Gen	-
3N39..44	IC	Reference amplifier	-		-
3N45	Ge-PNP	Tetrode, 60V, 12A, 75W	-	Sem	-
3N46	Ge-PNP	=3N45: 80V	-	Sem	-
3N47	Ge-PNP	=3N45: 40V	-	Sem	-
3N48	Ge-PNP	=3N45: 60V	-	Sem	-
3N49	Ge-PNP	=3N45: 15A, 94W	38	Gpd,Sem	-
3N50	Ge-PNP	=3N46: 15A, 94W	38	Gpd,Sem	-
3N51	Ge-PNP	=3N47: 15A, 94W	38	Gpd,Sem	-
3N52	Ge-PNP	=3N48: 15A, 94W	38	Gpd,Sem	-
3N56	Si-NPN	Tetrode, 18V, 0,03A, 0,15W	5	Tra	-
3N57	Si-NPN	Tetrode, 18V, 0,03A, 0,15W	5	Tra	-
3N58	Tetrode	40V, 0,1A (Ta=100°C)	5f	Gen	BR101, BRY20, BRY39, BRY21
3N59	Tetrode	=3N58	5f	Gen	BR101, BRY20, BRY39, BRY21
3N60	Tetrode	=3N58	5f	Gen	BR101, BRY20, BRY39, BRY21
3N62	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N63	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N64	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N65	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N66	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N67	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N68(A)	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N69	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N70	Si-NPN	Chopper	5y$	Sld,Tdy	-
3N71	Si-NPN	Chopper, 15V	5z$	Sld,Tdy	-
3N72	Si-NPN	Chopper, 15V	5z$	Sld,Tdy	-
3N73	Si-NPN	Chopper, 15V	5z$	Sld,Tdy	-
3N74	Si-NPN	Chopper, 50V	5z$	Sld,Tdy,Tix	-
3N75	Si-NPN	Chopper, 50V	5z$	Sld,Tdy,Tix	-
3N76	Si-NPN	Chopper, 50V	5z$	Sld,Tdy,Tix	-
3N77	Si-NPN	Chopper, 40V	5z$	Sld,Tdy,Tix	-
3N78	Si-NPN	Chopper, 40V	5z$	Sld,Tdy,Tix	-
3N79	Si-NPN	Chopper, 40V	5z$	Sld,Tdy,Tix	-
3N80	Tetrode	40V, 0,2A, Igt/Ih<1/6mA	5a$	Gen	BRY20, BRY39, BRY21
3N81	Tetrode	65V, 0,2A	5a$	Gen	BRY39, BRY21
3N82	Tetrode	=3N81: 100V	5a$	Gen	BRY39, BRY21
3N83	Tetrode	70V, 0,05A, Igt/Ih<0,15/<4mA	5a$	Gen	MAS32, BRY39, BRY21
3N84	Tetrode	40V, 0,175A, Igkt/Ih<0,01/<2mA	5a$	Gen	BR101, BRY20, MAS32, BRY39, BRY21
3N85	Tetrode	=3N84: 100V	5a$	Gen	BRY39, BRY21
3N86	Tetrode	=3N81	5a$	Gen	→3N81
3N87	Si-NPN	Chopper, 20V, 10mA, 0,2W	5z$	Sld,Tdy	-
3N88	Si-NPN	Chopper, 20V, 10mA, 0,2W	5z$	Sld,Tdy	-
3N89	P-FET	Dual-Gate, 30V, Idss>0,5mA, Up<4V	5r=	Gie	-
3N90	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N91	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N92	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N93	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N94	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N95	Si-PNP	Chopper, 50V, 20mA, 0,3W	5y$	Tdy	-
3N96	P-FET	Dual, 30V, Idss>0,5mA, Up<4V	81cc	Six	-
3N97	P-FET	Dual, 30V, Idss>0,5mA, Up<4V	81cc	Six	-
3N98	MOS-N-FET-d	GenP, 32V, Idss>3,5mA, Up<6V	5g+	Rca	-
3N99	MOS-N-FET-d	GenP, 32V, Idss>5mA, Up<6V	5g+	Rca	-
3P1M	Thy-50Hz	100V, 3A (Tc=87°C), Igt/Ih<5/=5mA	13h$	NEC	X0609..TAG621, TAG622..
3P1MH..3P6MH	Thy-50Hz	=3P1M..3P6M: Igt/Ih <0,2/1mA	13h$	-	TAG108-..(TAG623-..TAG628-..)
3P2M	Thy-50Hz	=3P1M: 200V	13h$	-	X0609..TAG621, TAG622..
3P4J(Z)	Thy-50Hz	400V, 3A (Tc=103°C), Igt/Ih<0,1/<5mA	30h$	Nec	-

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3P4M	Thy-50Hz	=3P1M:400V	13h$	-	X0609..TAG621,TAG622..
3P5M	Thy-50Hz	=3P1M:500V	13h$	-	X0609..TAG621,TAG622..
3P6M	Thy-50Hz	=3P1M:600V	13h$	-	X0609..TAG621,TAG622..
3S4M	Thy-Fast	400V,3A(Tc=70°C),Igt<30mA	13h$	NEC	(TAG650S-..TAG655S-..CSF11-..)
3SF11	Tetrode	70V,0,1A,Ih<1mA	S	Mat	-
3SJ11	MOS-P-FET-e	Chopper,30V,10mA,Up=3..6,5V,<1ke	5g+	Nec	-
3SJ11A	MOS-P-FET-e	=3SJ11:50mA,Up=1,5..3V,<500e	5g+	-	-
3SK100	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss>0,5mA,Up<3V	25u	Mat	3SK66,3SK79,3SK87
3SK101	MOS-N-FET-d*	Dual-Gate,VHF,20V,Idss>3mA,Up<2,5V	25u	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK102	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>3mA,Up<3,5V	25u	Tos	BF900,BF980
3SK103	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<10mA,Up<1V	25u	Hit	BF980
3SK104(V)	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<20mA,Up<2V	25u	Hit	BF980
3SK107	MOS-N-FET-d	Dual-Gate,FM/VHF,20V,Idss>2,5mA,Up<3V	?42u	Sanyo	BF964,3SK49
3SK108	MOS-N-FET-e	Dual-Gate,FM/VHF,20V,Idss>3mA,Up<1,5V	?42u	-	-
3SK11	MOS-N-FET-d	Dual-Gate,20V,Idss>0,5mA,Up<8V	5r=	Hit	-
3SK112	GaAs-N-FET-d	Dual-Gate,UHF,10V,Idss>20mA,Up<3,7V	25u	Tos	-
3SK113	GaAs-N-FET-d	Dual-Gate,UHF,12V,Idss>10mA,Up<6V	25u	Tos	-
3SK114	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss>0mA,Up<1V	25u	Tos	3SK53
3SK115	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss>0mA,Up<1V	25u	Tos	3SK198
3SK116	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>2,5mA,Up<3V	44v	Mat	BF989,BF991,BF994,BF996
3SK117	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<6mA	44v	Mat	-
3SK118	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss>1mA,Up<1V	25u	Mat	-
3SK119	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss>0,8mA,Up<3V	25u	Mat	-
3SK12	MOS-N-FET-d	Dual-Gate,20V,Idss>0,5mA,Up<8V	5r=	Hit	-
3SK120	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss>2mA	25u	Mat	-
3SK121	GaAs-N-FETd*	Dual-Gate,UHF,10V,Idss>20mA,Up<4V	25u	Tos	-
3SK122	MOS-N-FET-d	Dual-Gate,VHF-Tuner,20V,Idss>7mA	25u	Nec	3SK74
3SK123	MOS-N-FET-d	Dual-Gate,UHF,18V,Idss>0,01mA,Up<2V	25u	Nec	3SK88
3SK125	MOS-N-FET-d	Dual-Gate,VHF/UHF,15V,Idss>1mA	25u	Mat	BF960,BF966
3SK126	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss>0mA,Up<1V	44v	Tos	3SK195
3SK127	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss>0mA,Up<1V	44v	Tos	3SK199
3SK128	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss>1mA	44x	Mat	-
3SK129	GaAs-N-FET-d	Dual-Gate,13V,Idss>8,5mA,Up<3,5V	25u	Mat	-
3SK13	MOS-N-FET-d	Dual-Gate,20V,Idss>2mA,Up<8V	5r=	Hit	-
3SK131	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>7mA,Up<2V	44v	Nec	-
3SK131-V10	N-FET	-	44	Nec	→3SK131
3SK131-V11	N-FET	-	44	Nec	→3SK131
3SK131-V12	N-FET	-	44	Nec	→3SK131
3SK132(A)	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,5mA,Up<2V	44v	Nec	-
3SK132-U32	N-FET	-	44	Nec	→3SK132
3SK132-U33	N-FET	-	44	Nec	→3SK132
3SK132-U42	N-FET	-	44	Nec	→3SK132
3SK132-U43	N-FET	-	44	Nec	→3SK132
3SK133(A)	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>10µA,Up<2V	44v	Nec	-
3SK134(A,B)	MOS-N-FET-d	Dual-Gate,UHF-Tuner,15(A,B:18)V	44v	Nec	-
3SK135(A)	MOS-N-FET-d	Dual-Gate,UHF-Tuner,15V,Idss>10µA	44v	Nec	3SK133
3SK136	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>5mA,Up<3V	44v	Hit	-
3SK137	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<20mA,Up<2V	44v	Hit	-
3SK137V	MOS-N-FET-d	=3SK137:VHF	44v	-	-
3SK138	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<10mA,Up<1V	44v	Hit	-
3SK139	MOS-N-FET-d	=3SK125:SMD	44v	Mat	-
3SK139-P	MOS-N-FET-d	-	44	Mat	→3SK139
3SK139-Q	MOS-N-FET-d	-	44	Mat	→3SK139
3SK14	MOS-N-FET-d	Chopper,20V,10mA,Idss=1mA,Up<5V	5g+	Nec	-
3SK140	GaAs-N-FET-d	Dual-Gate,UHF-TV-Tuner	44v	Tos	-
3SK141	GaAs-N-FET-d	=3SK129:SMD	44v	Mat	-
3SK142	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss=0,5..13mA	25u	Mat	3SK79,3SK87,3SK100
3SK143	MOS-N-FET-d	-	44	Mat	→2SK143
3SK143-O	MOS-N-FET-d	-	44	Mat	→3SK143
3SK143-P	MOS-N-FET-d	-	44	Mat	→3SK143
3SK143-Q	MOS-N-FET-d	-	44	Mat	→3SK143
3SK144	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss>0,8mA	44v	Mat	-
3SK144-Q	MOS-N-FET-d	-	44	Mat	→3SK144
3SK144-R	MOS-N-FET-d	-	44	Mat	→3SK144

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3SK145	MOS-N-FET-d	Dual-Gate, UHF, 13,5V, Idss=0..6mA	25u	Tos	-
3SK146	N-FET	-	44	Tos	→3SK146
3SK15(A)	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5r=	Mit	-
3SK150	MOS-N-FET-d	Dual-Gate, VHF/UHF, 15V, Idss>3mA	25u	Tos	BF980
3SK151	MOS-N-FET-d	-	44	Tos	→3SK151
3SK152	MOS-N-FET-d	Dual-Gate, VHF/UHF, 13,5V, Idss=0..6V	25u	Tos	-
3SK153	N-FET	-	44	Tos	→3SK153
3SK154	MOS-N-FET-d	-	44	Hit	→3SK15
3SK156	MOS-N-FET-d	Dual-Gate, VHF, 12V, Idss=0..12mA	25u	Hit	-
3SK159	MOS-N-FET-d	Dual-Gate, VHF/UHF, 13,5V, Idss=0..6mA	25u	Tos	-
3SK16	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5r=	Mit	-
3SK160	N-FET	-	44	Tos	→3SK160
3SK162	MOS-N-FET-d	Dual-Gate, VHF, 12V, Idss=0..12mA	44v	Hit	-
3SK163	MOS-N-FET	Sw, 15V, 100mA, Uon<5,5V	44(SubDSG)	Son	-
3SK164	GaAs-N-FET-d	Dual-Gate, UHF, 12V, Idss>10mA	44v	Son	-
3SK165	GaAs-N-FET-d	Dual-Gate, UHF, 8V, Idss>20mA	44v	Son	-
3SK166	GaAs-N-FET-d	Dual-Gate, UHF, 8V, Idss>20mA	44v	Son	-
3SK167	GaAs-N-FET-d	Dual-Gate, UHF-V/M, 12V, Idss>10mA	44v	Sanyo	-
3SK167-2	N-FET	-	44	Sanyo	→3SK167
3SK167-3	N-FET	-	44	Sanyo	→3SK167
3SK167-4	N-FET	-	44	Sanyo	→3SK167
3SK167-5	N-FET	-	44	Sanyo	→3SK167
3SK168	GaAs-N-FET-d	Dual-Gate, UHF-Tuner, 12V, Idss>10mA	42t	Sanyo	-
3SK169	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>1,5mA	44v	Mat	-
3SK169-P	MOS-N-FET-d	-	44	Mat	→3SK169
3SK169-Q	MOS-N-FET-d	-	44	Mat	→3SK169
3SK17	MOS-N-FET-d	Dual-Gate, 25V, Idss<10mA, Up<9V	5r=	Mit	-
3SK171	GaAs-N-FET-d	-	44	Hit	→3SK171
3SK173	MOS-N-FET-d	Dual-Gate, CATV, 18V, Idss=0,5..10mA	25u	Nec	-
3SK174	GaAs-N-FET-d	Dual-Gate, UHF, 13V, Idss=5..40mA	25u	Nec	-
3SK176(A)	MOS-N-FET-d	=3SK173: SMD	44v	Nec	-
3SK179	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss>7mA	44v	Nec	-
3SK179-V01	N-FET	-	44	Nec	→3SK179
3SK179-V02	N-FET	-	44	Nec	→3SK179
3SK179-V03	N-FET	-	44	Nec	→3SK179
3SK18	MOS-N-FET-d	Dual-Gate, 15V, Idss<5mA, Up<6V	5r	Mit	-
3SK180	MOS-N-FET-d	Dual-Gate, FM/VHF, 15V, Idss>2,5mA	44v	Sanyo	-
3SK180-4	N-FET	-	44	Sanyo	→3SK180
3SK180-5	N-FET	-	44	Sanyo	→3SK180
3SK180-6	N-FET	-	44	Sanyo	→3SK180
3SK181	MOS-N-FET-e	Dual-Gate, FM/VHF, 15V	44v	Sanyo	-
3SK181-4	N-FET	-	44	Sanyo	→3SK181
3SK181-5	N-FET	-	44	Sanyo	→3SK181
3SK181-6	N-FET	-	44	Sanyo	→3SK181
3SK182	MOS-N-FET-d	-	44	Hit	→3SK182
3SK183	GaAs-N-FET-d	Dual-Gate, UHF, 13V, Idss>8,5mA, Up<6V	25u	Mat	-
3SK184	GaAs-N-FET-d	=3SK183: SMD	44v	Mat	-
3SK184-P	GaAs-N-FET-d	-	44	Mat	→3SK184
3SK184-Q	GaAs-N-FET-d	-	44	Mat	→3SK184
3SK184-R	GaAs-N-FET-d	-	44	Mat	→3SK184
3SK184-S	GaAs-N-FET-d	-	44	Mat	→3SK184
3SK186	MOS-N-FET-d	Dual-Gate, UHF, 12V, Idss=0..4V	44v	Hit	-
3SK187	GaAs-N-FET	Dual-Gate, 20V, Idss=8,5..130mA	44v	Mat	-
3SK188	MOS-N-FET-d	-	44	Hit	→3SK188
3SK189	GaAs-N-FET-d	Dual-Gate, UHF, 13V, Idss>8,5mA	44v	Sanyo	-
3SK19	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss<5mA, Up<6V	5r	Mit	-
3SK190	GaAs-N-FET-d	=3SK189:	42t	Sanyo	-
3SK191	GaAs-N-FET-d	Dual-Gate, UHF, 12V, Idss>10mA	44v	Hit	-
3SK192	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>1mA	44v	Mat	3SK193
3SK193	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>1mA	44v	Mat	3SK192
3SK193-P	MOS-N-FET-d	-	44	Mat	→3SK193
3SK193-Q	MOS-N-FET-d	-	44	Mat	→3SK193
3SK194	MOS-N-FET-d	Dual-Gate, VHF/UHF-Tuner, 15V, 35mA, Idss=0..10mA, Up<1,5V	44v	Hit	-
3SK195	MOS-N-FET-d	Dual-Gate, VHF, 13,5V, Idss>0mA	44v	Tos	3SK126

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3SK196	MOS-N-FET-d	Dual-Gate,VHF/UHF-Tuner,12V,35mA,Idss=0..1mA,Up<1,5V,F<4,5dB(900MHz)	44v		Hit-
3SK197	MOS-N-FET-d	Dual-Gate,VHF-TV-Tuner,12V,35mA,Idss=1..10mA,Up<1V,F<2,5dB(200MHz)	44v		Hit-
3SK198	MOS-N-FET-d	Dual-Gate, UHF, 13,5V, Idss>0mA	25u	Tos	3SK115
3SK199	N-FET	-	44	Tos	→3SK199
3SK20	MOS-N-FET-d	Dual-Gate, GenP, 20V, Idss>0,5mA, Up<3,5V	5r	Hit	3SK66, 3SK79, 3SK87, 3SK100
3SK200	MOS-N-FET-d	Dual-Gate, UHF, 15V, Idss>4mA	44v	Mat	-
3SK201	MOS-N-FET-d	Dual-Gate, UHF, 13V, 50mA, Idss=8,5..35mA, Up<6V	44v	Mat	-
3SK202	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss>0,8mA, Up<3V	25u	Mat	-
3SK203	GaAs-N-FET-d	Dual-Gate, UHF, 10V, Idss=8..60mA	25u	Nec	-
3SK204	GaAs-N-FET-d	=3SK203: SMD	44v	Nec	-
3SK205	GaAs-N-FET-d	Dual-Gate, UHF, 10V, Idss=10..80mA	25u	Nec	-
3SK207	MOS-N-FET-d	Dual-Gate, UHF, 13,5V, Idss>0V	44v	Tos	-
3SK21	MOS-N-FET-d	Dual-Gate, Chopper, 20V, Idss>3mA	5r	Hit	-
3SK212	GaAs-N-FET-d	Dual-Gate, UHF, TV-Tuner, 10V, 15mA	44v	Rhm	-
3SK215	GaAs-N-FET-d	TV-UHF, 12V, 1mA, Idss>6mA	44	Tos	-
3SK216	GaAs-N-FET-d	TV-UHF, 12V, 1mA, Idss>4mA	44	Tos	-
3SK217	MOS-N-FET-d	-	44	Hit	→3SK217
3SK219	MOS-N-FET-d	Dual-Gate, VHF, 15V, 30mA, Idss=0..8mA, Up=-1,5..+0,5V	44v	Mat	-
3SK22	N-FET	Dual-Gate, FM/VHF, 18V, Idss>3mA, Up<5V	5x=	Tos	-
3SK220	MOS-N-FET-d	Dual-Gate, VHF/UHF, 15V, 30mA	44v	Mat	-
3SK222	MOS-N-FET-d	Dual-Gate, VHF, 18V, 25mA	44v	NEC	-
3SK223	MOS-N-FET-d	Dual-Gate, CATV, 18V, 25mA	44v	Nec	-
3SK224	MOS-N-FET-d	Dual-Gate, CATV, 18V, 25mA	44v	Nec	-
3SK225	MOS-N-FET-d	Dual-Gate, FM..UHF, 13,5V, Idss>0V	44v	Tos	-
3SK226	MOS-N-FET-d	Dual-Gate, FM/VHF, 13,5V, Idss>0V	44v	Tos	-
3SK227	MOS-N-FET-d	Dual-Gate, UHF, 15V, 30mA, Idss=6..25mA, Up<1	44v	Mat	-
3SK228	GaAs-N-FET-d	-	44	Hit	→3SK228
3SK228(A)	GaAs-N-FET-d	Dual-Gate, UHF-TV-Tuner, 12V, 50mA, Idss=10..32V, Up<1,5V	44v	Hit	-
3SK229	GaAs-N-FET-d	Dual-Gate, UHF-TV-Tuner, 12V, 80mA, Idss=15..40mA, Up<3,5V	44v	Hit	-
3SK23	N-FET	Dual-Gate, FM/VHF, 15V, Idss>6mA, Up>1,8V	5x=	Tos	-
3SK230	MOS-N-FET-d	Dual-Gate, CATV, 18V, 25mA	44v	Nec	-
3SK231	MOS-N-FET-d	Dual-Gate, UHF, 18V, 25mA	44v	Nec	-
3SK232	MOS-N-FET-d	Dual-Gate, UHF, 12,5V, Idss<0,1mA	44v	Tos	-
3SK233	MOS-N-FET-d	Dual-Gate, UHF-TV-Tuner, 12V, 35mA, Idss=0..2mA, Up<0,8V	44v	Hit	-
3SK234	MOS-N-FET-d	Dual-Gate, VHF-TV-Tuner, 12V, 35mA, Idss=0..1mA, U=0..1V	44v	Hit	-
3SK235	MOS-N-FET-d	Dual-Gate, VHF/UHF-Tuner, 12V, 35mA, Idss=0..1mA, Up=0,1..1V	44v	Hit	-
3SK236	MOS-N-FET-d	-	44(2mm)	Hit	→3SK236
3SK237	MOS-N-FET-d	=3SK235:	44v(2mm)	Hit	-
3SK238	MOS-N-FET-d	-	44(2mm)	Hit	→3SK238
3SK239A	MOS-N-FET-d	-	44(2mm)	Hit	→3SK239A
3SK24	MOS-N-FET-d	→3SK39	5t	Mat	-
3SK240	GaAs-N-FET-d	Dual-Gate, UHF, 9V, Idss=6..20mA	44v	Tos	-
3SK241	GaAs-N-FET-d	Dual-Gate, VHF/UHF, 13V, 50mA, Idss=8,5..35mA, Up<-3,5	44v	Mat	-
3SK242	MOS-N-FET-d	Dual-Gate, VHF-Tuner, 20V, 25mA	44v(2mm)	NEC	-
3SK243	MOS-N-FET-d	Dual-Gate, CATV-Tuner, 18V, 25mA	44v(2mm)	NEC	-
3SK244	MOS-N-FET-d	Dual-Gate, UHF-Tuner, 18V, 25mA	44v(2mm)	Nec	-
3SK245	MOS-N-FET-d	Dual-Gate, UHF-Tuner, 18V, 25mA	44v(2mm)	NEC	-
3SK246	MOS-N-FET-d	Dual-Gate, FM/VHF, 18V, 25mA	44v(2mm)	NEC	-
3SK247	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss=0..10mA	44v	Mat	-
3SK248	MOS-N-FET-e	Dual-Gate, 10V, 100mA, Up<1,5V	44v	Sanyo	-
3SK249	MOS-N-FET-d	-	44(2mm)	Tos	→3SK249
3SK25	MOS-N-FET-d	→3SK39	5t	Mat	-
3SK250	GaAs-N-FET-d	Dual-Gate, UHF-TV-Tuner, 6V	44v	Tos	-
3SK252	MOS-N-FET-d	Dual-Gate, CATV-Tuner, 18V, 25mA	44v	Nec	NE93239
3SK253	MOS-N-FET-d	Dual-Gate, UHF-Tuner, 18V, 25mA	44v	Nec	-
3SK254	MOS-N-FET-d	=3SK252:	44v(2mm)	Nec	-
3SK255	MOS-N-FET-d	=3SK226:	44v(2mm)	Tos	-
3SK255	MOS-N-FET-d	=3SK253:	44v(2mm)	Nec	-
3SK256	MOS-N-FET-d	-	44(2mm)	Tos	→3SK256
3SK257	MOS-N-FET-d	-	44(2mm)	Tos	→3SK257
3SK258	MOS-N-FET-d	-	44(2mm)	Tos	→3SK258
3SK259	MOS-N-FET-d	-	44(2mm)	Tos	→3SK259
3SK260	MOS-N-FET-d	-	44(2mm)	Tos	→3SK260
3SK263	MOS-N-FET-d	Dual-Gate, FM/VHF, 15V, 30mA, Idss=2,5..24mA, F<2,2/Gp>18dB(200MHz)	44v		Sanyo-

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3SK263-4	MOS-N-FET-d	-	44	Sanyo	→3SK263
3SK263-5	MOS-N-FET-d	-	44	Sanyo	→3SK263
3SK263-6	MOS-N-FET-d	-	44	Sanyo	→3SK263
3SK264	MOS-N-FET-d	Dual-Gate,VHF-Tuner,15V,30mA,Idss=5..24mA,F<2,2/Gp>20dB(200MHz)	44v		Sanyo-
3SK264-5	MOS-N-FET-d	-	44	Sanyo	→3SK264
3SK264-6	MOS-N-FET-d	-	44	Sanyo	→3SK264
3SK265	MOS-N-FET-d	Dual-Gate,VHF/CATV,15V,30mA,Idss=5..24mA,F<2,2/Gp>23dB(200MHz)	44v		Sanyo-
3SK265-5	MOS-N-FET-d	-	44	Sanyo	→3SK265
3SK265-6	MOS-N-FET-d	-	44	Sanyo	→3SK265
3SK266	MOS-N-FET-d	Dual-Gate,13,5V,30mA,Idss>2,5mA	44v	Sanyo	-
3SK268	MOS-N-FET-d	-	44(2mm)	Mat	→3SK268
3SK269	MOS-N-FET-d	-	44(2mm)	Mat	→2SK269
3SK270	MOS-N-FET-d	-	44(2mm)	Mat	→3SK270
3SK271	MOS-N-FET-d	-	44(2mm)	Mat	→3SK271
3SK272	GaAs-N-FET-d	-	44(2mm)	Mat	→3SK272
3SK273	GaAs-N-FET-d	Dual-Gate,VHF/UHF,13V,50mA,Idss=8,5..35mA,Up<-3,5V	44v	Mat	-
3SK273-P	GaAs-N-FET-d	-	44	Mat	→3SK273
3SK273-Q	GaAs-N-FET-d	-	44	Mat	→3SK273
3SK273-R	GaAs-N-FET-d	-	44	Mat	→3SK273
3SK273-S	GaAs-N-FET-d	-	44	Mat	→3SK273
3SK274	GaAs-N-FET-d	-	44(2mm)	Tos	→3SK274
3SK275	GaAs-N-FET-d	-	44(2mm)	Tos	→3SK275
3SK276	MOS-N-FET-d	Dual-Gate,VHF/UHF,12V,25mA,Idss=0,5..10mA,Up<0,8V	44v	Hit	-
3SK28	N-FET	Dual-Gate,FM/VHF,18V,Idss>3,7mA	5x=	Tos	-
3SK282	GaAs-N-FET	MESFET,UHF,10V,800MHz	44	Tos	-
3SK283	GaAs-N-FET-d	Dual-Gate,UHF-TV-Tuner,6V,Idss=4..16mA,Up=0,5..1,5V	44v	Tos	-
3SK284	GaAs-N-FET-d	-	44(2mm)	Tos	→3SK284
3SK285	MOS-N-FET-d	Dual-Gate,UHF,13V,30mA,Idss=10..25mA,Up<1V	44v	Mat	-
3SK286	MOS-N-FET-d	Dual-Gate,VHF,15V,30mA,Idss=6..20mA,Up<1,5V	44v	Mat	-
3SK287	GaAs-N-FET	UHF,13V,800MHz	44	Mat	-
3SK288	MOS-N-FET-d	Dual-Gate,VHF,12V,25mA,Idss=1..10mA,Up<1V	44v	Hit	-
3SK29	MOS-N-FET-d	Chopper,GenP,20V,Idss=1mA,Up<5V	5g+	Nec	-
3SK290	MOS-N-FET-d	Dual-Gate,UHF,12V,25mA,Idss=0,5..10mA,Up<1V	44v(2mm)	Hit	-
3SK291	MOS-N-FET-e	Dual-Gate,TV UHF,12,5V,30mA	44v	Tos	-
3SK292	MOS-N-FET-e	Dual-Gate,TV VHF,12,5V,30mA	44v	Tos	-
3SK293	MOS-N-FET-e	=3SK291:	44v(2mm)	Tos	-
3SK294	MOS-N-FET-e	=3SK292:	44v(2mm)	Tos	-
3SK295	MOS-N-FET	Dual-Gate,UHF,12V,25mA,Up<1V	44v	Hit	-
3SK296	MOS-N-FET	-	44(2mm)	Hit	→3SK296
3SK297	MOS-N-FET	Dual-Gate,VHF,12V,25mA,Up<1V	44v	Hit	-
3SK298	MOS-N-FET	-	44(2mm)	Hit	→3SK298
3SK299	GaAs-N-FET	Dual Gate,UHF,13V,Idss 10-25mA	44v(2mm)	NEC	-
3SK299	GaAs-N-FET	Dual Gate,UHF,13V,Idss 5-15mA	44v(2mm)	NEC	-
3SK30(A)	N-FET	Dual-Gate,AM/FM,15V,Idss>3mA,Up<5V	5x	Hit	-
3SK300	MOS-N-FET-d	Dual-Gate,VHF/UHF,14V,25mA,Up<1V,F<4dB(900MHz),	44v	Hit	-
3SK301	MOS-N-FET-d	Dual-Gate,VHF,15V,30mA,Idss=5..23mA,Up<1,35V	44v	Mat	-
3SK302	MOS-N-FET-d	Dual-Gate,UHF,15V,30mA,Idss=0..10mA,Up<1,2V	44v	Mat	-
3SK303	MOS-N-FET-d	Dual-Gate,VHF,15V,30mA,Idss=0..10mA,Up<1,2V	44v	Mat	-
3SK304	MOS-N-FET-d	Dual-Gate,UHF,15V,30mA,Idss=0..10mA,Up<1,2V	44v	Mat	-
3SK305	MOS-N-FET-d	-	44(2mm)	Mat	→3SK305
3SK306	MOS-N-FET-d	-	44(2mm)	Mat	→3SK306
3SK307	MOS-N-FET-d	-	44(2mm)	Mat	→3SK307
3SK308	MOS-N-FET-d	-	44(2mm)	Mat	→3SK308
3SK309	GaAs-N-FET-d	Dual-Gate,UHF,6V,18mA,Idss=25..60mA,Up=0,2..1,5V	44v	Hit	-
3SK318	MOS-N-FET-d	Dual-Gate,UHF,6V,20mA,Up=0,5..1V	44(2mm)	Hit	-
3SK319	MOS-N-FET-d	=3SK318:	44	Hit	-
3SK32	MOS-N-FET-d	Dual-Gate,FM/VHF,20V,Idss<5mA,Up<2,5V	5u	Mat	3SK39,3SK70,3SK80
3SK320	MOS-N-FET-d	MES,Dual-Gate,UHF-M,6V,Idss=9..18mA,Up<0,8/1,4V	44v(2mm)	Tos	-
3SK33	MOS-N-FET-d	FM/VHF,25V,Idss>4mA,Up<4V	5m+	Nec	-
3SK35	MOS-N-FET-d*	Dual-Gate,VHF,20V,Idss>3mA,Up<4V	5t*+	Tos	BF350,BF900,3SK40
3SK37	MOS-N-FET-d*	Dual-Gate,VHF,20V,Idss>4mA,Up<3V	5t*+	Son	BF981,3SK37,3SK45,3SK61,3SK77
3SK38(A)	MOS-N-FET-e*	Dual-Gate,Chopper,10V,Up<3V	5r=	Tos	-
3SK39	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>1mA,Up<3V	5t*+	Mat	3SK70,3SK80
3SK40	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>4mA,Up<4V	5t*+	Nec	BF350..351,BF900,3N201..206..

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3SK41	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>4mA,Up<4V	St*+	Nec	BF350..351,BF900,3N201..206..
3SK44	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>3mA,Up<3,3V	St*+	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK45	MOS-N-FET-d	Dual-Gate,VHF,22V,Idss>4mA,Up<3V	St*+	Hit	BF981,3SK37,3SK61,3SK77
3SK47	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>4mA,Up<3V	St*+	Nec	BF980..982,3SK37,3SK45,3SK61,3SK77
3SK48	MOS-N-FET-d	Dual-Gate,UHF,18V,Idss>2mA,Up<3V	St*+	Son	BF960,BF965..966
3SK49	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>2,5mA,Up<3V	St*+	Mat	BF981,3SK37,3SK45,3SK61,3SK77
3SK51	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>8mA,Up<3V	St*+	Hit	3SK74
3SK53	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,1mA,Up<1,7V	St*+	Hit	3SK115
3SK55	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>3mA,Up<2,5V	St*+	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK59	MOS-N-FET-d*	Dual-Gate,FM/VHF,20V,Idss>3mA,Up<2,5V	St*+	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK60	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss<20mA,Up<1,7V	St*+	Hit	BF980..982,3SK47
3SK61	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>4mA,Up<3V	St*	Son	BF981,3SK37,3SK45,3SK77
3SK62	N-FET	Dual-Source,AF-Pre,20V,Idss<0,5mA	-	Tos	-
3SK63	MOS-N-FET-d*	Dual-Gate,VHF,20V,Idss>3mA,Up<2,5V	St*	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK66	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,5mA,Up<3V	St*+	Mat	3SK79,3SK87,3SK100
3SK70	MOS-N-FET-d	Dual-Gate,VHF/UHF,20V,Idss>1mA,Up<3V	St*	Hit	BF960,BF965..966,3SK48,3SK80
3SK71	N-FET	AF-Pre,20V,Idss<0,5mA	-	Nec	-
3SK72	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>2,5mA,Up<3V	25u	Mat	BF981,3SK37,3SK45,3SK61,3SK77
3SK73	MOS-N-FET-d*	Dual-Gate,VHF,20V,Idss>3mA,Up<2,5V	?42v	Tos	BF981,3SK37,3SK45,3SK61,3SK77
3SK74	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>7mA,Up<3V	25u	Nec	3SK51
3SK76	MOS-N-FET-d	Dual-Gate,14V,Idss>5mA,Up<1V	St*	Son	-
3SK77	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>3mA,Up<2,5V	?42v	Tos	BF981,3SK37,3SK45,3SK61
3SK78	MOS-N-FET-d	Dual-Gate,VHF/UHF,20V,Idss>3mA,Up<3,5V	St*,52y*	Tos	BF900,3N209..210
3SK79	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,5mA,Up<3V	25u	Mat	3SK66,3SK87,3SK100
3SK80	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>1mA,Up<3V	25u	Hit	BF960,BF965..966,3SK48,3SK70
3SK81	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss>5mA,Up<3V	25u	Hit	BF352..353,BF963,3SK51,3SK74
3SK82	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<20mA,Up<1,7V	25u	Hit	BF980
3SK83	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss<20mA,Up<1,7V	25u	Hit	BF982,3SK47
3SK85	MOS-N-FET-d	Dual-Gate,VHF,22V,Idss>4mA,Up<3V	25u	Hit	BF981,3SK37,3SK45,3SK61,3SK77
3SK87	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,5mA,Up<2V	25u	Nec	3SK66,3SK79,3SK100
3SK88	MOS-N-FET-d	Dual-Gate,UHF,20V,Idss>0,01mA,Up<2V	25u	Nec	3SK123
3SK90	MOS-N-FET-e	Dual-Gate,Chopper,20V,Up<3V	5r=	Tos	-
3SK95	MOS-N-FET-d	Dual-Gate,UHF,15V,Idss<30mA,Up<2V	25u	Hit	BF980
3SK96	MOS-N-FET-d	Dual-Gate,VHF,15V,Idss<30mA,Up<2V	25u	Hit	BF352..353,BF963,3SK81
3SK97	GaAs-N-FET	Dual-Gate,UHF,15,5V,Idss=3..80mA	25u	Mat	-
3SS3M	Thy-Fast	300V,3A(Tc=70°C),Igt<30mA	13h$	NEC	(TAG650S-..TAG655S-..CSF11-..)
3SS4M	Thy-Fast	=3SS3M:400V	13h$	-	(TAG650S-..TAG655S-..CSF11-..)
3TE120	Si-NPN	AM-Pow,90V,12A,Pq=50W(70MHz)	23a$	ITT	-
3TE130	Si-NPN	AM-Pow,90V,5A,Pq=30W(70MHz)	23a$	ITT	-
3TE220	Si-NPN	VHF-Pow,80V,5A,Pq=50W(150MHz)	23a$	ITT	-
3TE230	Si-NPN	VHF-Pow,80V,4A,Pq=30W(150MHz)	23a$	ITT	-
3TE240	Si-NPN	VHF-Pow,80V,3A,>200MHz	23a$	ITT	-
3TE440	Si-NPN	VHF/UHF-Pow,80V,1,5A,>350MHz	-	Itt	-
3TE450	Si-NPN	VHF/UHF-Pow,80V,0,5A,>350MHz	-	Itt	-
3TX002	Si-NPN	AM-Pow,100V,5A,>150MHz	23a$	ITT	-
3TX003	Si-NPN	AM-Pow,100V,5A,>150MHz	23a$	ITT	-
3TX004	Si-NPN	AM-Pow,60V,5A,>150MHz	23a$	ITT	-
3Z12..390	Z-Di/TVS	TAZ,12..390V,1,5kW(1µS)	31a	Tos	1N5635..5665,1N6273..6303
4					
40004	Ge-PNP	HF,40V,10mA,30MHz	4g	Sty	AF124..127,AF200
40005	Ge-PNP	HF,40V,10mA,100MHz	4g	Sty	AF124..125,AF200
40006	Ge-PNP	HF,40V,10mA,120MHz	4g	Sty	AF124..125,AF200
40022	Ge-PNP	AF,Sw-Pow,32V,5A,12,5W(Tc=75°)	23a$	Rca,Sty,++	AL102..103,AUY28,2N1539..48..
40050	Ge-PNP	AF,Sw-Pow,40V,5A,12,5W(Tc=75°)	23a$	Gpd,Rca,Sty	AL102..103,AUY28,2N1539..48..
40051	Ge-PNP	=40050:50V	23a$	Gpd,Rca,Sty	AL102..103,AUY28,2N1540..43..
40053	Si-NPN	?2N3053	2a$	Rca	→2N3053
40080	Si-NPN	AM-Driver,-/30V,0,25A,Pq>0,1W(27MHz)	2a$	Rca,Sty,++	MRF402,MRF8003
40081	Si-NPN	AM-Driver,60V,0,25A,Pq>0,4W(27MHz)	2a$	Rca,Sty,++	MRF402,MRF8003
40082	Si-NPN	AM-Driver,60V,1,5A,Pq>3W(27MHz)	2a$	Rca,Sty,++	-
40084	Si-NPN	AF,Sw,60V,1A,0,5A,>100MHz,<30/-nS	2a$	Rca,Sca,Sty	BSS26,BSS40..41,2N4014
40108	Si-Di	-	32a$	RCA	BYX42/300,BYX98/300
40108R..40116R	Si-Di	-	32b&	-	BYX42/..R,BYX98/..R
40109	Si-Di	-	32a$	-	BYX42/300,BYX98/300

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40110	Si-Di	-	32a$	-	BYX42/300,BYX98/300
40111	Si-Di	-	32a$	-	BYX42/300,BYX98/300
40112	Si-Di	-	32a$	-	BYX42/600,BYX98/600
40113	Si-Di	-	32a$	-	BYX42/600,BYX98/600
40114	Si-Di	-	32a$	-	BYX42/600,BYX98/600
40115	Si-Di	-	32a$	-	BYX42/900,BYX98/900
40116	Si-Di	-	32a$	-	BYX42/1200,BYX98/1200
40208	Si-Di	-	32a$	RCA	1N4525..30
40208R..40214R	Si-Di	-	32b&	-	D24/..C
40209	Si-Di	-	32a$	-	1N4525..30
40210	Si-Di	-	32a$	-	1N4525..30
40211	Si-Di	-	32a$	-	1N4526..30
40212	Si-Di	-	32a$	-	1N4526..30
40213	Si-Di	-	32a$	-	1N4527..30
40214	Si-Di	-	32a$	-	1N4527..30
40216	Thy-Fast	=S6431M	21b$	Rca	→S6431M
40217	Si-NPN	Sw,25V,0,3W,>200MHz	2a$	Rca,Sty	BSS11..12,BSX19..20,2N2368..69(A),..
40218	Si-NPN	Sw,25V,0,05A,0,3W,>200MHz	2a$	Rca,Sty	BSS11..12,BSX19..20,2N2368..69(A),..
40219	Si-NPN	Sw,40V,0,36W,>300MHz	2a$	Rca,Sty	BSS11,BSX19..20,2N2368..69(A),..
40220	Si-NPN	Sw,40V,0,2A,0,3W,>350MHz	2a$	Rca,Sty	BSS11,BSX19..20,2N2368..69(A),..
40221	Si-NPN	Sw,40V,0,36W,>300MHz	2a$	Rca,Sty	BSS11,BSX19..20,2N2368..69(A),..
40222	Si-NPN	Sw,25V,0,2A,0,3W,>200MHz	2a$	Rca,Sty	BSS11..12,BSX19..20,2N2368..69(A),..
40231	Si-NPN	AF,LN,18V,0,1A,0,5W,60MHz	2a$	Rca,Sca,Sty	BC169,BC184,BC239,BC549..
40232	Si-NPN	AF,LN,18V,0,1A,0,5W,60MHz	2a$	Rca,Sca,Sty	BC169,BC184,BC239,BC549..
40233	Si-NPN	AF,LN,18V,0,1A,0,5W,60MHz	2a$	Rca,Sca,Sty	BC169,BC184,BC239,BC549..
40234	Si-NPN	AF,LN,18V,0,1A,0,5W,60MHz	2a$	Rca,Sca,Sty	BC169,BC184,BC239,BC549..
40235	Si-NPN	VHF-Pre,1000MHz	5g	Nsc,Rca,Sca	BF314,BF496,BF502..503,BF505..
40236	Si-NPN	VHF-Mix,1000MHz	5g	Nsc,Rca,Sca	BF314,BF496,BF502..503,BF505..
40237	Si-NPN	VHF-Osc,1000MHz	5g	Nsc,Rca,Sca	BF314,BF496,BF502..503,BF505..
40238	Si-NPN	TV-IF-AGC,800MHz	5g	Nsc,Rca,Sca	BF198,BF225,BF310,BF367..
40239	Si-NPN	TV-IF,800MHz	5g	Nsc,Rca,Sca	BF199,BF224,BF311,BF373..
40240	Si-NPN	TV-IF-Out,800MHz	5g	Nsc,Rca,Sca	BF199,BF224,BF311,BF373..
40242	Si-NPN	FM-Preamp,900MHz	5g	Nsc,Rca,Sca	BF241,BF255,BF495,BF595..
40243	Si-NPN	FM-Mix,850MHz	5g	Nsc,Rca,Sca	BF241,BF255,BF495,BF595..
40244	Si-NPN	FM-Osc,800MHz	5g	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40245	Si-NPN	FM-IF,800MHz	5g	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40246	Si-NPN	FM-IF,800MHz	5g	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40250	Si-NPN	AF,Sw-Pow,50V,4A,29W,1MHz	22a$	Rca,Sgs,++	BD243,BD535,BD539A,2N3054..
40250V1	Si-NPN	=40250:	22a$o	-	→40250
40251	Si-NPN	AF,Sw-Pow,50V,15A,117W,0,5MHz	23a$	Rca,Sgs,++	BD315,BD545A,BDX13,2N3055..
40253	Ge-PNP	AF-Dr/Out,25V,0,5A,0,125W	2a	Rca,Sty	AC128,AC152..153,AC188,2SB405..
40254	Ge-PNP	AF-Pow,32V,5A,12,5W(Tc=75°)	23a$	Gpd,Rca,++	AL102..103,AUY28,2N1539..48..
40255	Si-NPN	AF,Sw-Pow,450/350V,1A,10W,>20MHz	43a$	Rca,Sty	BD410,BUW40(A,B),TIP49..50..
40256	Si-NPN	=40255:300/250V	43a$	Rca,Sty	BD410,BUW40(A,B),TIP47..50..
40261	Ge-PNP	AM-Pre/Mix/Osc,40MHz	2a	Rca,Sty	AF124..127,AF200
40262	Ge-PNP	AM-IF,30MHz	2a	Rca,Sty	AF124..127,AF200
40263	Ge-PNP	AF,20V,0,05A,0,12W	2a	Rca,Sty	AC125,AC126,AC151
40264	Si-NPN	AF/Vid-Out,300/300V,0,1A,4W,25MHz	?22	Rca,Sty	(BF459,BF859,2SC1505..1507,..)
40268	Ge-PNP	HF,25V,0,1A,0,1W,>250MHz	2a	Rca,Sty	(AF139,AF239(S))
40269	Ge-PNP	AF,Sw,25V,0,1A,0,15W,>4MHz	2a	Rca,Sty	AC125..126,AC151,ASY26..27
40279	Si-NPN	=2N3375:Hi-rel	49a	Rca,Ssi	→2N3375
40280	Si-NPN	VHF-Dr/Out,36V,0,5A,Pq>1W(175MHz)	2a$	Rca,Sca,Sty	BFQ42,BFR98,BLW16,BLY61
40281	Si-NPN	VHF-Pow,36V,1A,Pq>4W(175MHz)	49a*	Rca,Sca,Sty	BLY57,BLY78,2N3926
40282	Si-NPN	VHF-Pow,36V,2A,Pq>12W(175MHz)	49a*	Rca,Sca,Sty	BLY58,2N3927
40283	Si-NPN	Sw,60V,1A,0,4W,<30/45nS	2a$	Rca,Sca,Sty	2N4014
40290	Si-NPN	FM/VHF-Dr/Out,50V,0,5A,Pq>2W(135MHz)	2a$	Rca,Sty,++	BFW46,BLY33,2N3924
40291	Si-NPN	FM/VHF-Pow,50V,0,5A,Pq>2W(135MHz)	49a	Rca,Sty,++	BLY55
40292	Si-NPN	FM/VHF-Pow,50V,1,25A,Pq>6W(135MHz)	49a	Rca,Sty,++	BLY57,2N3926
40294	Si-NPN	=2N2857:Hi-rel	5g	Rca,Sty	→2N2857
40295	Si-NPN	=2N2708:Hi-rel	5g	Rca,Sty	→2N2708
40296	Si-NPN	=2N3839:Hi-rel	5g	Rca,Sty	→2N3839
40305	Si-NPN	=2N3553:Hi-rel	2a$	Rca,Ssi,Sty	→2N3553
40306	Si-NPN	=2N3375:Hi-rel	49a	Rca,Ssi,Sty	→2N3375
40307	Si-NPN	=2N3632:Hi-rel	49a	Rca,Ssi,Sty	→2N3632

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40309(L,S)	Si-NPN	AF-Driver,-/18V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC140..141,BC300..302,2N3053..
40309V1	Si-NPN	=40309(L,S):	2a$o	-	(BD137,BD228,BD517,BD527,..)
40309V2	Si-NPN	=40309(L,S):	43a$	-	(BD137,BD228,BD517,BD527,..)
40310	Si-NPN	AF-Pow,-/35V,4A,29W,0,75MHz	22a$	Rca,Sty,++	BD243,BD533,BD539,BD947..
40310V1	Si-NPN	AF-Pow,-/35V,4A,29W,0,75MHz	22a$o	-	BD243,BD533,BD539,BD947..
40311(L,S,V1,V2)	Si-NPN	=40309:-/30V	-	Rca,Sty,++	→40309(L,S,V1,V2)
40312(V1)	Si-NPN	=40310:60V	22a$(o)	Rca,Sty,++	BD243A,BD535,BD539A,BD949..
40313	Si-NPN	AF-Pow,300V,2A,35W	22a$	Rca,Sty	BUX67A..C,TIP75(A..C),2SC782..
40314(L,S)	Si-NPN	AF-Driver,-/40V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC140..141,BC300..302,2N3053..
40314V1	Si-NPN	=40314(L,S):	2a$o	-	(BD137,BD228,BD517,BD527,..)
40314V2	Si-NPN	=40314(L,S):	43a$	-	(BD137,BD228,BD517,BD527,..)
40315(L,S,V1,V2)	Si-NPN	=40314:-/35V	-	Rca,Sty,++	→40314(L,S,V1,V2)
40316	Si-NPN	AF-Pow,40V,4A,29W,0,75MHz	22a$	Rca,Sty,++	BD243A,BD535,BD539A,BD949..
40317(L,S,V1,V2)	Si-NPN	=40309:-/40V	-	Rca,Sty,++	→40309(L,S,V1,V2)
40318	Si-NPN	AF-Pow,300V,2A,35W	22a$	Rca,Sty,++	BUX67A..C,TIP75(A..C),2SC782..
40319(L,S)	Si-PNP	AF-Driver,-/40V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC160..161,BC303..304,2N2303..
40319V1	Si-PNP	=40319(L,S):	2a$o	-	(BD138,BD229,BD518,BD528,..)
40319V2	Si-PNP	=40319(L,S):	43a$	-	(BD138,BD229,BD518,BD528,..)
40320(L,S,V1,V2)	Si-NPN	=40314:B>40	-	Rca,Sty,++	→40314(L,S,V1,V2)
40321(L,S)	SI-NPN	AF/Vid,300V,1A,1W	2a$	Rca,Sty,++	BFQ38..39,BSS48..49,2N3440,2SC1861+
40321V1	Si-NPN	=40321(L,S):	2a$o	-	(BD410,BUV63,BUW40,TIP47..50,..)
40321V2	Si-NPN	=40321(L,S):	43a$	-	(BD410,BUV63,BUW40,TIP47..50,..)
40322	Si-NPN	=40318	22a$	Rca,Sty,++	→40318
40323(L,S,V1,V2)	Si-NPN	=40309	-	Rca,Sty,++	→40309(L,S,V1,V2)
40324	Si-NPN	=40310	22a$	Rca,Sty,++	→40310
40325	Si-NPN	AF-Pow,35V,15A,117W	23a$	Rca,Sty,++	BD315,BD545,BD745,2N3055..
40326(L,S,V1,V2)	SI-NPN	=40309:-/40V	-	Rca,Sty,++	→40309(L,S,V1,V2)
40327(L,S,V1,V2)	Si-NPN	=40321	-	Rca,Sty,++	→40321(L,S,V1,V2)
40328	Si-NPN	=40318	22a$	Rca,Sty,++	→40318
40329	Ge-PNP	AF,Sw,25V,0,1A,0,125W	2a	Rca,Sty	AC125..126,AC151,ASY26..27
40340	Si-NPN	FM/VHF-Pow,60V,3,3A,Pq>25W(50MHz)	49a*	Rca,Ssi	-
40341	Si-NPN	FM/VHF-Pow,70V,3,3A,Pq>30W(50MHz)	49a*	Rca,Ssi	-
40342	Si-NPN	HF-Pow,65V,3A,23W	49a	Rca	-
40343	Si-NPN	HF-Pow,65V,3A,23W	49a	Rca	-
40346(L,S)	Si-NPN	AF,Sw,175V,1A,1W,>10MHz	2a$	Rca,Sty,++	BFQ38..39,BSS48..49,2N3440,2SC1861+
40346V1	Si-NPN	=40346(L,S):	2a$o	-	(BD410,BUW40,2SC3117,2SD669,..)
40346V2	Si-NPN	=40346(L,S):	43a$	-	(BD410,BUW40,2SC3117,2SD669,..)
40347(L,S)	Si-NPN	AF,Sw,60V,1,5A	2a$	Rca,Sty,++	BCX40,BSS42..43,(BD139,BD529,..)
40347V1	Si-NPN	=40347(L,S):	2a$o	-	(BD139,BD237,BD529,BD843,..)
40347V2	Si-NPN	=40347(L,S):	43a$	-	(BD139,BD237,BD529,BD843,..)
40348(L,S,V1,V2)	Si-NPN	=40347:90V	-	Rca,Sty,++	→40347(L,S,V1,V2)
40349(L,S,V1,V2)	SI-NPN	=40347:160V	-	Rca,Sty,++	(BD410,BD443A,2SC3117,2SD669,..)
40350	Si-NPN	UHF	5g	Sty	BF377..378,BF689,BF763,2N2857..
40351	Si-NPN	UHF	5g	Sty	BF377..378,BF689,BF763,2N2857..
40352	Si-NPN	UHF	5g	Sty	BF377..378,BF689,BF763,2N2857..
40354	Si-NPN	Vid,-/150V,0,05A,0,5W,100MHz	2a	Rca	BF297..299;BFR87..89,2SC3467..
40355	Si-NPN	=40354:1W	2a$o	Rca	BF297..299,BFR87..89,2SC3467..
40359	Ge-PNP	AF,20V,0,05A,0,12W	2a	Rca,Sty	AC125..126,AC151,ASY26..27
40360(L,S)	Si-NPN	AF-Driver,70V,0,7A,1W,100MHz,B>40	2a$	Rca,Sty,++	BC140..141,BC300..301,2N1990..
40360V1	Si-NPN	=40360(L,S):	2a$o	-	(BD139,BD230,BD519,BD529,..)
40360V2	Si-NPN	=40360(L,S):	43a$	-	(BD139,BD230,BD519,BD529,..)
40361(L,S,V1,V2)	Si-NPN	=40360:B>70	-	Rca,Sty,++	→40360(L,S,V1,V2)
40362(L,S)	Si-PNP	AF-Driver,70V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC161,BC303,BCX60,2SA606..
40362V1	Si-PNP	=40362(L,S):	2a$o	-	(BD140,BD231,BD520,BD530,..)
40362V2	Si-PNP	=40362(L,S):	43a$	-	(BD140,BD231,BD520,BD530,..)
40363	Si-NPN	AF-Pow,70V,15A,115W,0,7MHz	23a$	Rca,Sty,++	BD315,BD545B,BD745B,2N3055..
40364	Si-NPN	AF-Pow,60V,7A,35W,15MHz	22a$	Rca,Sty,++	BD243A,BD543A,BD807,2N6315..16..
40366(L,S)	Si-NPN	=2N2102:Hi-rel	2a$	Rca,Sty,++	→2N2102
40366V1	Si-NPN	=40366(L,S):	2a$o	-	(BD424,2SC2275,2SC2384,2SC2690(A)..)
40366V2	Si-NPN	=40366(L,S):	43a$	-	(BD424,2SC2275,2SC2384,2SC2690(A)..)
40367(L,S)	Si-NPN	AF-Dr/Out,100V,1,5A,1W	2a$	Rca,Sty	BCX40,BSW66..68,BSX46..47..
40367V1	Si-NPN	=40367(L,S):	2a$o	-	(BD139,BD230,BD529,BD843,..)
40367V2	Si-NPN	=40367(L,S):	43a$	-	(BD139,BD230,BD529,BD843,..)
40368	Si-NPN	AF,Sw-Pow,100V,3A,25W	2a$	Rca,Sty	(BD241C,BD539C,BD939,2SD712,..)

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40369	Si-NPN	AF,Sw-Pow,100V,6A,75W	23a$	Rca,Ssi,Sty	BD245C,BDV91,BDX91,2N5758..59..
40372	Si-NPN	=2N3054:5,8W	22a$o	Rca,Sty	→2N3054
40373	Si-NPN	=2N3441:5,8W	22a$o	Rca,Sty	→2N3441
40374	Si-NPN	=2N3583:5,8W	22a$o	Rca,Sty	→2N3583
40375	Si-NPN	=2N3878:5,8W	22a$o	Rca,Sty	→2N3878
40378	Thy-50Hz	=S2600B	2a$	Rca	→S2600B
40379	Thy-50Hz	=S2600D	2a$	Rca	→S2600D
40385(L,S)	Si-NPN	=2N3439:Hi-rel	2a$	Rca,Sca	→2N3439
40385V1	Si-NPN	=2N3439:	2a$o	-	→2N3439
40385V2	Si-NPN	=2N3439:	43a$	-	→2N3439
40389	Si-NPN	=2N3053:3,5W	2a$o	Rca,Sty	→2N3053
40390	Si-NPN	=2N3440:3,5W	2a$o	Rca,Sty	→2N3440
40391	Si-PNP	=2N4037:3,5W	2a$o	Rca,Sty,++	→2N4037
40392	Si-NPN	=2N3053:7W(Tc=25°)	43a$	Rca,Sty,++	→2N3053
40393	Si-NPN	=2N3440:10W(Tc=25°)	43a$	Rca	→2N3440
40394	Si-PNP	=2N4037:7W(Tc=25°)	43a$	Rca,Sty,++	→2N4037
40395	Ge-PNP	AF-Pow,18V,0,5A,0,3W	2a	Rca,Sca,Sty	AC128,AC152..153,AC188
40396	Ge-NPN	AF-Pow,18V,0,5A,0,3W	2a	Rca,Sty	AC127,AC176,AC187
40397	Si-NPN	AF,25V,0,2A,0,5W,50MHz,B>165	2a$	Rca,Sca,Sty	BC168,BC183,BC238,BC548..
40398	Si-NPN	=40397:a>75	2a$	Rca,Sca,Sty	BC168,BC183,BC238,BC548..
40399	Si-NPN	=40397:18V	2a$	Rca,Sca,Sty	BC168,BC183,BC238,BC548..
40400	Si-NPN	=40397:18V,a>75	2a$	Rca,Sca,Sty	BC168,BC183,BC238,BC548..
40403	Ge-PNP	AF,Sw,30V,0,2A,0,2W,<850/1200nS	2a	Rca,Sty	AC125..126,AC151,ASY26
40404	Si-NPN	FM/VHF,40V,0,5A,Pq>0,05W(86MHz)	2a$	Rca,Sty	MRF604,2SC2053
40405	Si-NPN	VHF,40V,0,5A,Pq>0,2W(172MHz)	2a$	Rca,Sty,++	MRF604,2SC2053
40406(L,S)	Si-PNP	AF-Driver,-/50V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC161,BC303..304,2SA606
40407(L,S)	Si-NPN	AF-Driver,-/50V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC140..141,BC300..302,2N3053,..
40408(L,S)	Si-NPN	AF-Driver,-/90V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC141,BC300..301,2N1990,2N2405..
40409	Si-NPN	AF-Dr/Out,90V,0,7A,3W(Ta=50°)	2a$o	Rca,Sty,++	(BD139,BD230,BD529,BD829,..)
40410	Si-PNP	AF-Dr/Out,90V,0,7A,3W(Ta=50°)	2a$o	Rca,Sty,++	(BD140,BD231,BD530,BD830,..)
40411	Si-NPN	AF-Pow,90V,30A,150W,0,8MHz	23a$	Rca,Sty,++	BDW30,BDY29,MJ802,2SD797
40412(L,S)	Si-NPN	AF,Sw,-/250V,1A,10W(Tc=25°),>10MHz	2a$	Rca,Sty,++	BUX55,BUY59..60,2N5092,2N5095..
40412V1	Si-NPN	=40412:4W	2a$o	-	(BD410,BUW40(A,B),TIP47..50,..)
40412V2	Si-NPN	=40412:4W	43a$	-	(BD410,BUW40(A,B),TIP47..50,..)
40413	Si-NPN	UHF,>700MHz	5g	Rca	BF377..378,BF689,BF763,2N2857..
40414	Si-NPN	UHF,>1000MHz	5g	Rca	BF377..378,BF689,BF763,2N2857..
40421	Ge-PNP	AF-Pow,75V,5A,12,5W(Tc=80°)	23a$	Gpd,Rca	AL102..103,AUY28,2N1541..43..
40422	Si-NPN	AF/Vid-Pow,300V,0,15A,8W(Tc=75°)	22a$	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40423	Si-NPN	=40422:	22a$o	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40424	Si-NPN	AF/Vid-Pow,300V,0,15A,8W(Tc=75°)	22a$	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40425	Si-NPN	=40424:	22a$o	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40426	Si-NPN	AF/Vid-Pow,300V,0,15A,8W(Tc=75°)	22a$	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40427	Si-NPN	=40426:	22a$o	Rca,Sca,Sty	2SC1505..1507,2SC1755..1757,2SC1905,..
40428	Ge-Diode	Stabi,0,27SV(80(A)	2c	Rca	-
40429	Triac	=T2700B	22a$	Rca	→T2700B
40430	Triac	=T2700D	22a$	Rca	→T2700D
40431	Triac	+Diac,200V,6A,Ih<30mA	2a$	Rca	-
40432	Triac	=40431:400V	2a$	Rca	-
40439	Ge-PNP	TV-HD,320V,10A,5W(Tc=55°)	23a$	Gpd,Rca	AU106,AU109,AU111..112,2N5325
40440	Ge-PNP	TV-HD,200V,10A,5W(Tc=55°)	23a$	Gpd,Rca	AU107,AU113,AU213,2N5324
40442	Ge-Diode	TV-Damper,200V,7A	23	Rca	-
40444	Si-NPN	HF-Pow,120/60V,20A,Pq>20W(2,5MHz)	23a$	Rca,Sca	-
40446	Si-NPN	AM-Pow,-/60V,1,5A,Pq>3W(27MHz)	43a$	Rca,Sca,Sty	(2SC2020,2SC2029)
40450	Si-NPN	=2N3241A:1W	2a$o	Rca,Sty	→2N3241A
40451	Si-NPN	=2N3242A:1W	2a$o	Rca,Sty	→2N3242A
40452	Si-NPN	=2N4074:1W	2a$o	Rca,Sty	→2N4074
40453	Si-NPN	=40397:1W	2a$o	Rca,Sty	→40397
40454	Si-NPN	=40398:1W	2a$o	Rca,Sty	→40398
40455	Si-NPN	=40399:1W	2a$o	Rca,Sty	→40399
40456	Si-NPN	=40400:1W	2a$o	Rca,Sty	→40400
40457	Si-NPN	GenP,25V,1A,0,5W,>80MHz	2a$	Sca	BC337..338,BC635,BC637,BC639..
40458	Si-NPN	GenP,Sw,60V,1A,0,5W,<75/575nS	2a$	Rca,Sca,Sty	BC637,BC639,BSS26,BSS40..41..
40459	Si-NPN	=40458:1W	2a$o	Rca,Sty	BC637,BC639,BSS26,BSS40..41..
40460	MOS-N-FET-d	AF/HF/Sw,25V,Idss<9mA	5g+	Rca	-

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40461	MOS-N-FET-d	AF/HF/Sw,25V,Idss=4..14mA	5g+	Rca	-
40462	Ge-PNP	AF,Sw-Pow,40V,5A,12,W(Tc=75°)	23a$	Gpd,Rca,Sty	AL102..103,AUY28,2N1539..48..
40464	Si-NPN	AF,Sw-Pow,35V,5A,40W,>2MHz	23a$	Rca,Sca	BD245,BDV91,BDX91,2N4914..15..
40465	Si-NPN	=40464:40V	23a$	Rca,Sca	BD245,BDV91,BDX91,2N4914..15..
40466	Si-NPN	=40464:50V	23a$	Rca,Sca	BD245,BDV91,BDX91,2N4914..15,..
40467(A)	MOS-N-FET-d	VHF-Pre,20V,Idss>10mA,Up<8V	5m+	Rca	-
40468(A)	MOS-N-FET-d	AM/FM-Pre.,20V,Idss>5mA	5m+	Rca	-
40469	Si-NPN	VHF,AGC,700MHz	5k	Rca,Sty	BF225,BF314,BF502,BF505,BF506..
40470	Si-NPN	TV-IF-AGC,700MHz	5k	Rca,Sty	BF198,BF225,BF310,BF367,BF596..
40471	Si-NPN	TV-IF-AGC,700MHz	5k	Rca,Sty	BF198,BF225,BF310,BF367,BF596..
40472	Si-NPN	VHF-Pre,900MHz	5k	Nsc,Rca,Sca	BF225,BF314,BF502,BF505,BF507..
40473	Si-NPN	VHF-Mix,900MHz	5k	Nsc,Rca,Sca	BF224,BF314,BF503,BF505,BF507..
40474	Si-NPN	VHF-Osc,900MHz	5k	Nsc,Rca,Sca	BF224,BF314,BF503,BF505,BF507..
40475	Si-NPN	TV-IF,800MHz	5k	Nsc,Rca,Sca	BF199,BF224,BF311,BF373,BF597..
40476	Si-NPN	TV-IF,800MHz	5k	Nsc,Rca,Sca	BF199,BF224,BF311,BF373,BF597..
40477	Si-NPN	TV-IF,800MHz	5k	Nsc,Rca,Sca	BF199,BF224,BF311,BF373,BF597..
40478	Si-NPN	FM-Preamp,800MHz	5k	Nsc,Rca,Sca	BF241,BF255,BF495,BF595..
40479	Si-NPN	FM-Mix,800MHz	5k	Nsc,Rca,Sca	BF241,BF255,BF495,BF595..
40480	Si-NPN	FM-Osc,800MHz	5k	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40481	Si-NPN	FM-IF,860MHz	5k	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40482	Si-NPN	FM-IF,860MHz	5k	Nsc,Rca,Sca	BF240,BF254,BF494,BF594..
40485	Triac	200V,6A,Igt/Ih<40/<30mA	2a$	Rca	-
40486	Triac	=40485:400V	2a$	Rca	-
40487	Ge-PNP	AM-Mix,40MHz	2a	Rca,Sty	AF124..127,AF200
40488	Ge-PNP	AM-Osc,30MHz	2a	Rca,Sty	AF124..127,AF200
40489	Ge-PNP	AM-IF,30MHz	2a	Rca,Sty	AF124..127,AF200
40490	Ge-PNP	AF,20V,0,02A,0,12W	2a	Rca,Sty	AC125..126,AC151
40491	Si-NPN	AF-Pow,300V,0,15A,3,8W,25MHz	22a$o	Rca,Sty,++	2SC1505..1507,2SC1755..1757,2SC1905
40495	Si-Di	-	34	RCA	BY126..127,BY133..134,1N4004..07..
40500	Si-NPN	GenP,30V,0,2A,0,5W,>80MHz	2a$	Sca	BC168,BC183,BC238,BC548..
40502	Triac	=T2710B	22a$o	Rca	→T2710B
40503	Triac	=T2710D	22a$o	Rca	→T2710D
40504	Thy-50Hz	=S2710B	22a$o	Rca	→S2710B
40505	Thy-50Hz	=S2710D	22a$o	Rca	→S2710D
40506	Thy-50Hz	=S2710M	22a$o	Rca	→S2710M
40507	Thy-50Hz	=S2600B	2a$o	Rca	→S2600B
40508	Thy-50Hz	=S2600D	2a$o	Rca	→S2600D
40509	Triac	=40485	2a$o	Rca	→40485
40510	Triac	=40486	2a$o	Rca	→40486
40511	Triac	=40431	2a$o	Rca	→40431
40512	Triac	=40432	2a$o	Rca	→40432
40513	Si-NPN	AF,Sw-Pow,45V,6A,83W,>0,8MHz	-	Rca	BD245,BDV91,2SD895..896
40514	Si-NPN	=40513	-	Rca	BD245,BDV91,2SD895..896
40517	Si-NPN	UHF,LN,1900MHz	5g	Rca,Sty	BF377..378,BF689,BF763,2SC2570..
40518	Si-NPN	=40517:Hi-rel	5g	Rca,Sty	(BF377..378,BF689,BF763,2SC2570..)
40519	Si-NPN	VHF/UHF-Dr,40V,0,5A,Pq=0,3W(240MHz)	2a	Rca,Ssi,Sty	(BFS50,MRF515,2SC2852)
40525	Triac	=T2300A	2a$	Rca	→T2300A
40526	Triac	=T2300B	2a$	Rca	→T2300B
40527	Triac	=T2300D	2a$	Rca	→T2300D
40528	Triac	=T2302A	2a$	Rca	→T2302A
40529	Triac	=T2302B	2a$	Rca	→T2302B
40530	Triac	=T2302D	2a$	Rca	→T2302D
40531	Triac	=T2310A	2a$o	Rca	→T2310A
40532	Triac	=T2310B	2a$o	Rca	→T2310B
40533	Triac	=T2310D	2a$o	Rca	→T2310D
40534	Triac	=T2312A	2a$o	Rca	→T2312A
40535	Triac	=T2312B	2a$o	Rca	→T2312B
40536	Triac	=T2312D	2a$o	Rca	→T2312D
40537(L,S)	Si-PNP	AF-Driver,55V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC161,BC303..304,2SA606
40538(L,S)	Si-PNP	AF-Driver,55V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC161,BC303..304,2SA606
40539(L,S)	Si-NPN	AF-Driver,55V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC140..141,BC300..302,2N1990..
40542	Si-NPN	AF-Pow,50V,6A,83W,>0,8MHz	-	Rca	BD245,BDV91,2SD718,2SD895..896..
40543	Si-NPN	AF-Pow,60V,8A,83W,>0,8MHz	-	Rca	BD245A,BDV91,2SC3256,2SD718..
40544	Si-NPN	AF-Dr/Out,50V,0,7A,7W,100MHz	43a$	Rca,Sty,++	(BD137,BD228,BD525,BD827,..)

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40546	Si-NPN	AF-Pow,250V,0,15A,8W(Tc=75°),B>50	22a$	Rca,Sty	2SC1505..1507,2SC1755..1757,2SC1905
40547	Si-NPN	=40546:B>20	22a$	Rca,Sty	2SC1505..1507,2SC1755..1757,2SC1905
40553	Thy-Fast	=S3700B	22a$	Rca	→S3700B
40554	Thy-Fast	=S3700D	22a$	Rca	→S3700D
40555	Thy-Fast	=S3700M	22a$	Rca	→S3700M
40559(A)	MOS-N-FET-d	AM/FM-Mix,20V,Idss>5mA,Up<6V	5m+	Rca	-
40561	Ge-Diode	=1N3847	?34	Rca	→1N3847
40562	Ge-Diode	=1N3848	?34	Rca	→1N3848
40563	Ge-Diode	=1N3849	?34	Rca	→1N3849
40564	Ge-Diode	=1N3850	?34	Rca	→1N3850
40565	Ge-Diode	=1N3851	?34	Rca	→1N3851
40566	Ge-Diode	=1N3852	?34	Rca	→1N3852
40567	Ge-Diode	=1N3853	?34	Rca	→1N3853
40568	Ge-Diode	=1N3854	?34	Rca	→1N3854
40569	Ge-Diode	=1N3855	?34	Rca	→1N3855
40570	Ge-Diode	=1N3856	?34	Rca	→1N3856
40571	Ge-Diode	=1N3857	?34	Rca	→1N3857
40572	Ge-Diode	=1N3858	?34	Rca	→1N3858
40573	Ge-Diode	=1N3859	?34	Rca	→1N3859
40574	Ge-Diode	=1N3860	?34	Rca	→1N3860
40575	Triac	=T47008	22a$	Rca	→T47008
40576	Triac	=T47000	22a$	Rca	→T47000
40577	Si-NPN	=2N3118:Hi-rel	2a$	Rca,Ssi	→2N3118
40578	Si-NPN	=2N3866:Hi-rel	2a$	Rca,Sty	→2N3866
40581	Si-NPN	AM-Dr/Out,60V,1,5A,Pq>3,5W(27MHz)	2a$	Rca,Sca	(2SC2020,2SC2029)
40582	Si-NPN	AM-Pow,60V,1,5A,Pq>3,5W(27MHz)	43a$	Rca,Sca	(2SC2020,2SC2029)
40583	Diac	Ub=27..37,Ib<0,05mA,Itsm=2A	31	Rca	1N5761,N413M,BR100,D3202Y,D0201YR
40594(L,S)	Si-NPN	=RCA1A03	2a$	Rca,Sca,Sty	→RCA1A03
40595(L,S)	Si-PNP	=RCA1A04	2a$	Rca,Sca,Sty	→RCA1A04
40600	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss=18mA,Up=2V	5t+	Rca	BF351..353,3N201..206,3N211..213..
40601	MOS-N-FET-d	Dual-Gate,VHF,20V,Idss=18mA,Up=2V	5t+	Rca	BF351..353,3N201..206,3N211..213..
40602	MOS-N-FET-d	Dual-Gate,TV-IF,20V,Idss=18mA,Up=2V	5t+	Rca	BF351..353,3N201..206,3N211..213..
40603	MOS-N-FET-d	Dual-Gate,FM-Amp,20V,Idss=18mA,Up=2V,	5t+	Rca	BF351..353,3N201..206,3N211..213..
40604	MOS-N-FET-d	Dual-Gate,FM-Mix,20V,Idss=18mA,Up=2V	5t+	Rca	BF351..353,3N201..206,3N211..213..
40605	Si-NPN	VHF/UHF-Out,65V,0,33A,Pq>1,5W(500MHz)	2a$	Rca,Ssi	BFR97,2SC2852
40608	Si-NPN	VHF-A,40V,0,4A,>700MHz	2a$	Rca,Ssi	BFS50,MRF629,2N3948,2SC2852..
40611(L,S)	Si-NPN	AF-Driver,-/25V,0,7A,1W,100MHz	2a$	Rca,Sty,++	BC140..141,BC300..302,2N3053..
40612	Ge-PNP	AF-Pow,25V,5A,12,5W	23a$	Gpd,Rca,Sty	AL102..103,AUY28,2N1529..48..
40613	Si-NPN	AF-Pow,-/25V,4A,36W	17j$	Rca,Sty,++	BD243,BD533,BD539,BD947..
40616(L,S)	Si-NPN	AF-Driver,-/32V,0,7A,1W,100MHz	2a$	Rca,Sty	BC140..141,BC300..302,2N3053..
40618	Si-NPN	AF-Pow,-/30V,4A,36W,>0,8MHz	17j$	Rca,Ssi,Sty	BD243,BD533,BD539,BD947..
40621	SI-NPN	AF-Pow,-/32V,4A,36W,>0,8MHz	17j$	Rca,Ssi,Sty	BD243,BD533,BD539,BD947..
40622	Si-NPN	=40621:-/40V	17j$	Rca,Ssi,Sty	BD243,BD533,BD539,BD947..
40623	Ge-PNP	AF-Pow,45V,5A,12,5W	23a$	Gpd,Rca,Sty	AL102..103,AUY28,2N1529..48..
40624	Si-NPN	AF-Pow,-/45V,6A,50W	17j$	Rca,Ssi,Sty	BD243A,BD543A,BD797,BD807..
40625	Si-NPN	AF-Dr/Out,-/45,1A,3,5W	2a$o	Rca,Ssi,Sty	(BD137,BD228,BD525,BD827,..)
40626	Ge-PNP	AF-Pow,55V,5A,12,5W	23a$	Gpd,Rcs,Sty	AL102..103,AUY28,2N1540..48..
40627	Si-NPN	AF-Pow,-/55V,6A,50W	17j$	Rca,Ssi	BD243B,BD543B,BD799,BD809..
40628	Si-NPN	AF-Dr/Out,-/55V,1A,3,5W	2a$o	Rca,Ssi,Sty	(BD139,BD230,BD527,BD829,..)
40629	Si-NPN	AF-Pow,35V,4A,36W	17j$	Rca,Ssi	BD243,BD533,BD539,BD947..
40630	Si-NPN	AF-Pow,40V,4A,36W	17j$	Rca,Ssi	BD243,BD533,BD539,BD947..
40631	Si-NPN	AF-Pow,45V,4A,36W	17j$	Rca,Ssi	BD243,BD533,BD539A,BD947..
40632	Si-NPN	AF-Pow,60V,6A,50W	17j$	Rca,Ssi	BD243A,BD543A,BD797,BD807..
40633	Si-NPN	AF-Pow,75V,8A,83W	-	Rca,Sty	BD245B,BD545B,BDV93,2SD718..
40634(L,S)	Si-PNP	=RCA1A05	2a$	Rca,Sty,++	→RCA1A05
40635(L,S)	Si-NPN	=RCA1A06	2a$	Rca,Sty,++	→RCA1A06
40636	Si-NPN	=RCA1B01	23a$	Rca,Sty,++	→RCA1B01
40637	Si-NPN	VHF-Dr,30V,0,1A,0,3W,300MHz	2a$	Rca,Ssi,Sty	BFX59
40637A	Si-NPN	=40637:36V,0,2A,0,75W	2a$	-	2SC2053,2SC2851,(BFR36)
40638	Triac	=40485	2a$o	Rca	→40485
40639	Triac	=40486	2a$o	Rca	→40486
40640	Thy-Fast	=S3705M	22a$	Rca	→S3705M
40641	Thy-Fast	=S3706M	22a$	Rca	→S3706M
40642	Si-Di	-	31a	RCA	D2601EF

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40643	Si-Di	-	31a	RCA	D2601DF
40644	Si-Di	-	31a	RCA	D2600EF
40654	Thy-50Hz	=S2600B	2a$	Rca	→S2600B
40655	Thy-50Hz	=S2600D	2a$	Rca	→S2600D
40656	Thy-50Hz	=S2620B	2a$o	Rca	→S2620B
40657	Thy-50Hz	=S2620D	2a$o	Rca	→S2620D
40658	Thy-50Hz	=S2610B	2a$o	Rca	→S2610B
40659	Thy-50Hz	=S2610D	2a$o	Rca	→S2610D
40660	Triac	=T6401B	29b$	Rca	→T6401B
40661	Triac	=T6401D	29b$	Rca	→T6401D
40662	Triac	=T6411B	21b$	Rca	→T6411B
40663	Triac	=T6411D	21b$	Rca	→T6411D
40664	Triac	450V,6A,Igt<50mA	2a$	Rca	-
40665	Si-NPN	VHF/UHF-Pow,65V,1A,Pq>13,5W(175MHz)	49a*	Rca,Ssi,Sty	BLY60,2N3632
40666	Si-NPN	VHF/UHF-Pow,65V,0,5A,Pq>3W(400MHz)	49a*	Rca,Ssi,Sty	(BLY60,2N3632)
40667	Triac	=40664	2a$o	Rca	-
40668	Triac	=T2800B	17h$	Rca	→T2800B
40669	Triac	=T2800D	17h$	Rca	→T2800D
40670	Triac	=T2800M	17h$	Rca	→T2800M
40671	Triac	=T6401M	29b$	Rca	→T6401M
40672	Triac	=T6411M	21b$	Rca	→T6411M
40673	MOS-N-FET-d	Dual-Gate,VHF/UHF,20V,Idss>5mA,Up<4V	St+	Rca	3N209..210
40675	Si-NPN	AM-Pow,(SSB),+Stabi-Diode,65V,10A	-	Rca	-
40680	Triac	=S6420A	54b	Rca	→S6420A
40681	Triac	=S6420B	54b	Rca	→S6420B
40682	Triac	=S6420D	54b	Rca	→S6420D
40683	Triac	=S6420M	54b	Rca	→S6420M
40684	Triac	=T2313A	2a$o	Rca	→T2313A
40685	Triac	=T2313B	2a$o	Rca	→T2313B
40686	Triac	=T2313D	2a$o	Rca	→T2313D
40687	Triac	=T2313M	2a$o	Rca	→T2313M
40688	Triac	=T6420B	54b	Rca	→T6420B
40689	Triac	=T6420D	54b	Rca	→T6420D
40690	Triac	=T6420M	54b	Rca	→T6420M
40691	Triac	=T2301B	2a$	Rca	→T2301B
40692	Triac	=T2301D	2a$	Rca	→T2301D
40693	Triac	=T2316A	2a$o	Rca	→T2316A
40694	Triac	=T2316B	2a$o	Rca	→T2316B
40695	Triac	=T2316D	2a$o	Rca	→T2316D
40696	Triac	=T2306A	2a$	Rca	→T2306A
40697	Triac	=T2306B	2a$	Rca	→T2306B
40698	Triac	=T2306D	2a$	Rca	→T2306D
40699	Triac	=T6406B	29b$	Rca	→T6406B
40700	Triac	=T6406D	29b$	Rca	→T6406D
40701	Triac	=T6406M	29b$	Rca	→T6406M
40702	Triac	=T6416B	21b$	Rca	→T6416B
40703	Triac	=T6416D	21b$	Rca	→T6416D
40704	Triac	=T6416M	21b$	Rca	→T6416M
40705	Triac	=T6407B	29b$	Rca	→T6407B
40706	Triac	=T6407D	29b$	Rca	→T6407D
40707	Triac	=T6417B	21b$	Rca	→T6417B
40708	Triac	=T6417D	21b$	Rca	→T6417D
40709	Triac	=T6407M	29b$	Rca	→T6407M
40710	Triac	=T6407M	29b$	Rca	→T6407M
40711	Triac	=T4106B	29b$	Rca	→T4106B
40712	Triac	=T4106D	29b$	Rca	→T4106D
40713	Triac	=T4116B	21b$	Rca	→T4116B
40714	Triac	=T4116D	21b$	Rca	→T4116D
40715	Triac	=T4706B	22a$	Rca	→T4706B
40716	Triac	=T4706D	22a$	Rca	→T4706D
40717	Triac	=T4107B	29b$	Rca	→T4107B
40718	Triac	=T4107D	29b$	Rca	→T4107D
40719	Triac	=T4117B	21b$	Rca	→T4117B
40720	Triac	=T4117D	21b$	Rca	→T4117D

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40721	Triac	=T2806B	17h$	Rca	→T2806B
40722	Triac	=T2806D	17h$	Rca	→T2806D
40723	Triac	=T2606DF	2a$	Rca	→T2606DF
40724	Triac	=T2616DF	2a$o	Rca	→T2616DF
40725	Triac	=T2606B	2a$o	Rca	→T2606B
40726	Triac	=T2606D	2a$	Rca	→T2606D
40727	Triac	=T2706B	22a$	Rca	→T2706B
40728	Triac	=T2706D	22a$	Rca	→T2706D
40729	Triac	=T2716B	22a$o	Rca	→T2716B
40730	Triac	=T2716D	22a$o	Rca	→T2716D
40731	Triac	=40485:Igt/Ih<45/15mA	2a$o	Rca	-
40732	Triac	=40486:Igt/Ih<45/15mA	2a$o	Rca	-
40733	Triac	=40485:Igt/Ih<45/15mA	2a$o	Rca	-
40734	Triac	=40486:Igt/Ih<45/15mA	2a$o	Rca	-
40735	Thy-Fast	=2N3653:600V,=S7430M	21b$	Rca	→S7430M,2N3653
40737	Thy-50Hz	100V,6,3A(Tc=85°C),Igt/Ih<15/<20mA	29b$	Rca	T6N100H,T8N100H,BStD4026,S6200A..
40738	Thy-50Hz	=40737:200V	29b$	-	T6N200H,T8N200H,BStD4026,S6200B..
40739	Thy-50Hz	=40737:400V	29b$	Rca	T6N400H,T8N400H,BStD4026,S6200D..
40740	Thy-50Hz	=40737:600V	29b$	Rca	T6N600H,T8N600H,BStD4040,S6200M..
40741	Thy-50Hz	=40737:	21b$	-	T6N100C,T8N100C,BStD4126,S6210A..
40742	Thy-50Hz	=40738:	21b$	-	T6N200C,T8N200C,BStD4126,S6210B..
40743	Thy-50Hz	=40739:	21b$	-	T6N400C,T8N400C,BStD4126,S6210D..
40744	Thy-50Hz	=40740:	21b$	-	T6N600C,T8N600C,BStD4140,S6210M..
40745	Thy-50Hz	=40737:Iso	54b	-	S6220A,C230A3
40746	Thy-50Hz	=40738:Iso	54b	-	S6220B,C230B3
40747	Thy-50Hz	=40739:Iso	54b	-	S6220D,C230D3
40748	Thy-50Hz	=40740:Iso	54b	-	S6220M,C230M3
40749	Thy-50Hz	=S6200A	29b$	Rca	→S6200A
40750	Thy-50Hz	=S6200B	29b$	Rca	→S6200B
40751	Thy-50Hz	=S6200D	29b$	Rca	→S6200D
40752	Thy-50Hz	=S6200M	29b$	Rca	→S6200M
40753	Thy-50Hz	=S6210A:	21b$	-	→S6210A
40754	Thy-50Hz	=S6210B:	21b$	-	→S6210B
40755	Thy-50Hz	=S6210D:	21b$	-	→S6210D
40756	Thy-50Hz	=S6210M:	21b$	-	→S6210M
40757	Thy-50Hz	=S6220A:Iso	54b	-	→S6220A
40758	Thy-50Hz	=S6220B:Iso	54b	-	→S6220B
40759	Thy-50Hz	=S6220D:Iso	54b	-	→S6220D
40760	Thy-50Hz	=S6220M:Iso	54b	-	→S6220M
40761	Triac	=T2311B	2a$o	Rca	→T2311B
40762	Triac	=T2311D	2a$o	Rca	→T2311D
40766	Triac	=T2301A	2a$	Rca	→T2301A
40767	Triac	=T2311A	2a$o	Rca	→T2311A
40768	Thy-Fast	=S3701M	22a$	Rca	→S3701M
40769	Triac	=T2304B	2a$	Rca	→T2304B
40770	Triac	=T2304D	2a$	Rca	→T2304D
40771	Triac	=T2305B	2a$	Rca	→T2305B
40772	Triac	=T2305D	2a$	Rca	→T2305D
40773	Triac	200V,2,5A,Igt/Ih<40/<30mA	2a$	Rca	T2306B,T2303B,TAG208-200
40774	Triac	=40773:400V	2a$	Rca	T2306D,T2303D,TAG208-400
40775	Triac	=T4105B	29b$	Rca	→T4105B
40776	Triac	=T4105D	29b$	Rca	→T4105D
40777	Triac	=T4115B	21b$	Rca	→T4115B
40778	Triac	=T4115D	21b$	Rca	→T4115D
40779	Triac	=T4104B	29b$	Rca	→T4104B
40780	Triac	=T4104D	29b$	Rca	→T4104D
40781	Triac	=T4114B	21b$	Rca	→T4114B
40782	Triac	=T4114D	21b$	Rca	→T4114D
40783	Triac	=T4103B	29b$	Rca	→T4103B
40784	Triac	=T4103D	29b$	Rca	→T4103D
40785	Triac	=T4113B	21b$	Rca	→T4113B
40786	Triac	=T4113D	21b$	Rca	→T4113D
40787	Triac	=T6405B	29b$	Rca	→T6405B
40788	Triac	=T6405D	29b$	Rca	→T6405D

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40789	Triac	=T6415B	21b$	Rca	→T6415B
40790	Triac	=T6415D	21b$	Rca	→T6415D
40791	Triac	=T6404B	29b$	Rca	→T6404B
40792	Triac	=T6404D	29b$	Rca	→T6404D
40793	Triac	=T6414B	21b$	Rca	→T6414B
40794	Triac	=T6414D	21b$	Rca	→T6414D
40795	Triac	=T4101M	29b$	Rca	→T4101M
40796	Triac	=T4111M	21b$	Rca	→T4111M
40797	Triac	=T4100M	29b$	Rca	→T4100M
40798	Triac	=T4110M	21b$	Rca	→T4110M
40799	Triac	=T4121B:Iso	54b	Rca	→T4121B
40800	Triac	=T4121D:Iso	54b	Rca	→T4121D
40801	Triac	=T4121M:Iso	54b	Rca	→T4121M
40802	Triac	=T4120B:Iso	54b	Rca	→T4120B
40803	Triac	=T4120D:Iso	54b	Rca	→T4120D
40804	Triac	=T4120M:	54b	Rca	→T4120M
40805	Triac	=T6421B:Iso	54b	Rca	→T6421B
40806	Triac	=T6421D:Iso	54b	Rca	→T6421D
40807	Triac	=T6421M:Iso	54b	Rca	→T6421M
40808	Si-Di	-	31a	RCA	BYV36C,BYV95C,BYW95C,1N4247..49,..
40809	Ge-P/N	=AC127+AC128	2a	Rca	→AC127/128
40810	Thy-50Hz	100V,1,5A(Tc=75°C),Igt/Ih<15/<20mA	2a$	Rca	TAG612-100,TAG613-100,TAG606-100,..
40811	Thy-50Hz	=40810:200V	2a$	-	TAG612-200,TAG613-200,TAG606-200,..
40812	Thy-50Hz	=40810:400V	2a$	-	TAG612-400,TAG613-400,TAG606-400,..
40813	Thy-50Hz	=40810:600V	2a$	-	TAG612-600,TAG613-600,TAG606-600,..
40814	Si-NPN	=RCA1A07	2a$	Rca	→RCA1A07
40815	Si-PNP	=RCA1A08	2a$	Rca	→RCA1A08
40819	MOS-N-FET-d	Dual-Gate,VHF-Amp,25V,Idss>5mA,Up<4V	5t+	Rca	BF351,3N201..206,3N211..213
40820	MOS-N-FET-d	Dual-Gate,VHF-V,20V,Idss>0,5mA,Up<3V	5t+	Rca	3SK66,3SK79,3SK87,3SK100
40821	MOS-N-FET-d	Dual-Gate,VHF-Mix,20V,Idss>0,5mA,Up<3V	5t+	Rca	3SK66,3SK79,3SK87,3SK100
40822	MOS-N-FET-d	Dual-Gate,FM-Amp,20V,Idss>5mA,Up<4V	5t+	Rca	BF351,3N201..206,3N211..213
40823	MOS-N-FET-d	Dual-Gate,FM-Mix,20V,Idss>5mA,Up<4V	5t+	Rca	BF351,3N201..206,3N211..213
40829	Si-PNP	=2N5954:5.8W	22a$o	Rca	→2N5954
40830	Si-PNP	=2N5955:5.8W	22a$o	Rca	→2N5955
40831	Si-PNP	=2N5956:5.8W	22a$o	Rca	→2N5956
40832	Si-NPN	=40852	23a$	Rca	→40852
40833	Thy-50Hz	=S2600M	2a$	Rca	→S2600M
40834	Thy-50Hz	=S2620M	2a$o	Rca	→S2620M
40835	Thy-50Hz	=S2610M	2a$o	Rca	→S2610M
40836	Si-NPN	UHF-Osc,50V,0,2A,Pq=0,65W(2GHz)	Koax	Rca	-
40837	Si-NPN	UHF-Osc,50V,0,275A,Pq=1,35W(2GHz)	Koax	Rca	-
40841	MOS-N-FET-d	Dual-Gate,VHF,24V,Idss=10mA,Up=2V	5t+	Rca	BF351,3N201..206,3N211..213
40842	Triac	=T2801DF	17h$	Rca	→T2801DF
40850	Si-NPN	?2N3585	22a$	Rca,Sty,++	→2N3585
40851	Si-NPN	?2N6079	22a$	Rca,Sty,++	→2N6079
40852	Si-NPN	?2N5240	23a$	Rca,Sty,++	→2N5240
40853	Si-NPN	?2N5805	23a$	Rca,Sty,++	→2N5805
40854	Si-NPN	?2N6251	23a$	Rca,Sty,++	→2N6251
40867	Thy-50Hz	=S2800A	17h$	Rca	→S2800A
40868	Thy-50Hz	=S2800B	17h$	Rca	→S2800B
40869	Thy-50Hz	=S2800D	17h$	Rca	→S2800D
40871	Si-NPN	AF,Sw-Pow,120V,7A,40W,>4MHz	17j$	Rca	BD243D,BD543D,2SD550,2SD866
40872	Si-PNP	AF,Sw-Pow,120V,7A,40W,>4MHz	17j$	Rca	BD244D,BD544D,2SB870
40873	Si-NPN	AF,Sw-Pow,80V,7A,40W,>4MHz	17j$	Rca	BD243B,BD543B,BD799,BD809..
40874	Si-PNP	AF,Sw-Pow,80V,7A,40W,>4MHz	17j$	Rca	BD244D,BD544D,BD800,BD810..
40875	Si-NPN	AF,Sw-Pow,60V,7A,40W,>4MHz	17j$	Rca	BD243A,BD543A,BD797,BD807..
40876	Si-PNP	AF,Sw-Pow,60V,7A,40W,>4MHz	17j$	Rca	BD244A,BD544A,BD798,BD808..
40877	Si-NPN	AF,Sw-Pow,-/65V,10A,75W,7MHz	17j$	Rca	BD709,BD743B,BD809,BD909..
40878	Si-PNP	AF,Sw-Pow,-/65V,10A,75W,10MHz	17j$	Rca	BD710,BD744B,BD810,BD910..
40879	Si-NPN	AF,Sw-Pow,-/85V,10A,75W,7MHz	17j$	Rca	BD711,BD743C,BD911
40880	Si-PNP	AF,Sw-Pow,-/85V,10A,75W,10MHz	17j$	Rca	BD712,BD744C,BD912
40881	Si-NPN	AF,Sw-Pow,-/40V,10A,75W,7MHz	17j$	Rca	BD707,BD743A,BD807,BD907..
40882	Si-PNP	AF,Sw-Pow,-/40V,10A,75W,10MHz	17j$	Rca	BD708,BD744A,BD808,BD908..
40885	Si-NPN	=2N6175:	15g$o	Rca	→2N6175

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40886	Si-NPN	=2N6176:	15g$o	Rca	→2N6176
40887	Si-NPN	=2N6177:	15g$o	Rca	→2N6177
40888(U)	Thy-Fast	TV-HD, +750V, 3,2A(Tc=60°C), Igt<32mA	22a$	Rca	→S3703SF
40889(U)	Thy-Fast	TV-HD, +700V, 3,2A(Tc=60°C), Igt<45mA	22a$	Rca	→S3702SF
40890	Si-Di	-	34b&	RCA	D2103SF
40891	Si-Di	-	34b&	RCA	D2103S
40892	Si-Di	-	34b&	RCA	D2101S
40893	Si-NPN	UHF-Pow, 36V, 3A, Pq>15W(470MHz)	55s	Rca	BLW15, BLX69, 2SC1338, 2SC1404
40894	Si-NPN	AM/FM-Pre., 1400MHz	5g	Rca,Sca	BF225, BF314, BF502, BF505, BF507..
40895	Si-NPN	AM/FM-Mix 1400MHz	5g	Rca,Sca	BF225, BF314, BF502, BF505, BF507..
40896	Si-NPN	AM/FM-Osc, 1400MHz	5g	Rca,Sca	BF225, BF314, BF502, BF505, BF507..
40897	Si-NPN	AM/FM-IF, 1400MHz	5g	Rca,Sca	BF225, BF314, BF502, BF505, BF507..
40898	Si-NPN	UHF-Dr/Out, 45V, 0,35A, Pq>2W(2,3GHz)	Koax	Rca	-
40899	Si-NPN	UHF-Dr/Out, 45V, 1,5A, Pq>6W(2,3GHz)	Koax	Rca	-
40900	Triac	=T2850A	17h	Rca	→T2850A
40901	Triac	=T2850B	17h	Rca	→T2850B
40902	Triac	=T2850D	17h	Rca	→T2850D
40909	Si-NPN	UHF-Pow, 50V, 0,7A, Pq>2W(2GHz)	Koax	Rca	-
40910	Si-NPN	=2N6260: 5,8W	22a$o	Rca	→2N6260
40911	Si-NPN	=2N6261: 5,8W	22a$o	Rca	→2N6261
40912	Si-NPN	=2N6263: 5,8W	22a$o	Rca	→2N6263
40913	Si-NPN	=2N6264: 5,8W	22a$o	Rca	→2N6264
40915	Si-NPN	UHF, LN, 30V, 0,04A, 2900MHz	5g	Rca,Sca	BFR15, BFS55, 2SC2498, 2SC2570
40925	Triac	=T6400N:	29b$	Rca	→T6400N
40926	Triac	=T6410N:	21b$	Rca	→T6410N
40927	Triac	=T6420N: Iso	54b	Rca	→T6420N
40934	Si-NPN	UHF-Dr/Out, 36V, 0,5A, Pq>2W(470MHz)	51s	Rca	BLX66, 2SC1620
40936	Si-NPN	AM/SSB-Pow, 65V, 3,3A, Pep=20W(30MHz)	49a	Rca	-
40940	Si-NPN	UHF-Pow, 65V, 1,5A, Pq>5W(400MHz)	55s	Rca	BLW91, 2SC2893
40941	Si-NPN	UHF-Dr/Out, 55V, 0,4A, Pq>1W(400MHz)	51s	Rca	MRF509
40942	Thy-50Hz	=S2400A	2a$	Rca	→S2400A
40943	Thy-50Hz	=S2400B	2a$	Rca	→S2400B
40944	Thy-50Hz	=S2400D	2a$	Rca	→S2400D
40945	Thy-50Hz	=S2400M	2a$	Rca	→S2400M
40952	Thy-50Hz	=2N3873: 800V, =S6420N	54b	Rca	→2N3873, S6420N
40953	Si-NPN	VHF-Dr/Out, 36V, 0,33A, Pq>2W(156MHz)	2a$	Rca	BFW46, BLY33, MRF227, 2N3924
40954	Si-NPN	VHF-Pow, 36V, 4,5A, Pq>10W(156MHz)	55r	Rca	BLW38, BLY63, MRF209, 2N5591..
40955	Si-NPN	VHF-Pow, 36V, 5A, Pq>25W(156MHz)	55r	Rca	BLW20, BLW31, 2N6084
40956(R)	Si-Di	-	32a$/b&	RCA	D2540F(-R)
40957(R)	Si-Di	-	32a$/b&	RCA	D2540A(-R)
40958(R)	Si-Di	-	32a$/b&	RCA	D2540B(-R)
40959(R)	Si-Di	-	32a$/b&	RCA	D2540D(-R)
40960(R)	Si-Di	-	32a$/b&	RCA	D2540M(-R)
40964	Si-NPN	UHF-Dr/Out, 36V, 0,2A, Pq=0,44W(470MHz)	2a$	Rca,Sca	BFS50, MRF515, 2N3948
40965	Si-NPN	UHF-Dr/Out, 36V, 0,2A, Pq=0,44W(470MHz)	2a$	Rca,Sca	BFS50, MRF515, 2N3948
40967	Si-NPN	UHF-Dr/Out, 36V, 0,5A, Pq>2W(470MHz)	55r	Rca	BLX67, 2N5945, 2SC2104
40968	Si-NPN	UHF-Dr/Out, 36V, 1,5A, Pq>6W(470MHz)	55r	Rca	BLW14, BLW44, 2N5946, 2SC2105
40970	Si-NPN	UHF-Pow, 36V, Pq>30W(470MHz)	57s	Rca	BLU45/12, MRF646, 2SC2783
40971	Si-NPN	UHF-Pow, 36V, Pq>45W(136MHz)	57s	Rca	BLV75/12, 2SC2630, 2SC3147
40972	Si-NPN	VHF-Dr/Out, 36V, 0,33A, Pq>1,75W(175MHz)	2a$	Rca	BFW46, MRF227, 2N3924
40973	Si-NPN	VHF-Pow, 36V, 4,5A, Pq>10W(175MHz)	55r	Rca	BLY89, MRF209, 2N5591, 2N6082
40974	Si-NPN	VHF-Pow, 36V, 5A, Pq>25W(175MHz)	55r	Rca	BLW20, BLW31, 2N6084
40975	Si-NPN	FM/VHF-Osc/Dr, -/30V, 0,4A	2a$	Rca,Sca	BFR98, BLW16, BLY61, MRF607
40976	Si-NPN	FM/VHF-Dr/Out, -/30V, 0,5A	2a$	Rca,Sca	BFR98, BLW16, BLY61, MRF607
40977	Si-NPN	VHF-Pow, -/30V, 5A, Pq>6W(118MHz)	55r	Rca	BLW38, BLY63
40979	Si-NPN	=RCA1C10	17j$	Rca	→RCA1C10
40980	Si-PNP	=RCA1C11	17j$	Rca	→RCA1C11
40HF-10..-100	Si-Di	-	32a$	Motorola	BYX56/..BYX97/..
40HF-10R..100R	Si-Di	-	32b&	-	-
410	Si-NPN	AF, Sw-Pow, 200/200V, 7A, 125W, 4MHz	23a$	Rca	BUW87, BUX18(A,B), TIP160..162..
41002	Si-Di	-	34	RCA	D2101S
41004	MOS-P-FET-e	AF/HF/Sw, 30V, Up<4V	2e	Rca	-
41008	Si-NPN	UHF-Dr/Out, 36V, Pq>0,5W(470MHz)	51r	Rca	-
41008A	Si-NPN	=41008:	55r	-	-

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41009	Si-NPN	UHF-Dr/Out, 36V, Pq>2W(470MHz)	51r	Rca	-
41009A	Si-NPN	=41009:	55r	-	-
41010	Si-NPN	UHF-Pow, 36V, Pq>5W(470MHz)	55r	Rca	-
41012	Si-NPN	Sw, Pow, 120/80V, 20A, 175W, >40MHz	23a$	Rca	BUV10..12, BUW57..58, BUX10..12..
41013	Si-NPN	=41012: 160/125V	23a$	Rca	BUV11..12, BUW58, BUX11..12..
41014	Triac	=T2500B	17h$	Rca	→T2500B
41015	Triac	=T2500D	17h$	Rca	→T2500D
41017	Thy-Fast+Di	=S3800SF	22a$	Rca	→S3800SF
41018	Thy-Fast+Di	=S3800MF	22a$	Rca	→S3800MF
41019	Thy-Fast+Di	=S3800E	22a$	Rca	→S3800E
41020	Thy-Fast+Di	=S3800S	22a$	Rca	→S3800S
41021	Thy-Fast+Di	=S3800M	22a$	Rca	→S3800M
41022	Thy-Fast+Di	=S3800EF	22a$	Rca	→S3800EF
41023	Thy-Fast+Di	=S3800D	22a$	Rca	→S3800D
41024	Si-NPN	UHF-Dr/Out, 55V, 0,4A, Pq>1W(1GHz)	2a$	Rca	-
41025	Si-NPN	UHF-Pow, 50V, 0,35A, Pq>3W(1GHz)	55r	Rca	-
41026	Si-NPN	UHF-Pow, 50V, 1,5A, Pq>10W(1GHz)	55r	Rca	-
41027	Si-NPN	UHF-Pow, 45V, 0,35A, Pq>3W(1GHz)	55r	Rca	-
41028	Si-NPN	UHF-Pow, 45V, 1,5A, Pq>10W(1GHz)	55r	Rca	-
41038	Si-NPN	-/21V, Pq>0,75W	2a$	Rca	-
41039	Si-NPN	VHF-A, 40V, 0,25A, >2GHz	2a$	Rca,Sca	2SC1253, 2SC1366, 2SC1952
41042	Si-NPN	FM/VHF-Pow, 65V, 90W(Tc=75°)	55r	Rca	-
41044	Si-NPN	HF-Dr/Out, 40V, 5W(Tc=100°)	62b&	Rca	-
411	Si-NPN	=410: 300/300V	23a$	Rca	BUX18A,B, TIP160..162, 2SC2961..
413	Si-NPN	=410: 400/325V	23a$	Rca	BUX18B, TIP162, 2SC2625, 2SC2961..
41420	Thy-Fast+Di	?BStCC0146R	22a$	Rca	→BSTCC0146R
41500	Si-NPN	AF, Sw-Pow, 35V, 7A, 40W, >4MHz	17j$	Rca	BD243, BD543, BD795, BD805..
41501	Si-PNP	AF, Sw-Pow, 35V, 7A, 40W, >4MHz	17j$	Rca	BD244, BD544, BD796, BD806..
41502	Si-NPN	GenP, -/30V, 1A, 0,8W	2a$	Rca,Sca	BC140..141, BCX40, 2N1990, 2N2102..
41503	Si-PNP	GenP, -/30V, 1A, 0,8W	2a$	Rca,Sca	BC160..161, BCX60, 2SA606
41504	Si-NPN	AF, Sw-Pow, 35V, 4A, 36W, >0,8MHz	17j$	Rca	BD243, BD533, BD539, BD947..
41505	Si-NPN	AF, Sw-Pow, -/200V, 1A, 20W, 20MHz	15g$	Rca	(BD410, BUV63)
41506	Si-NPN	Sw, Pow, 200/200V, 3A, 100W	23a$	Rca,Sca	2SD632
41508	Si-NPN	Sw, Pow, -/140V, 30A, 150W	23a$	RCA	BD249F, BUW58, BUW73, 2SC2865(A)..
423	Si-NPN	=410: 400/325V	23a$	Rca	BUX18B, TIP162, 2SC2625, 2SC2961..
431	Si-NPN	=410: 400/325V	23a$	Rca	BUX18B, TIP162, 2SC2625, 2SC2961..
43104	Si-NPN	Sw, Pow, 160/140V, 16A, 150W, >0,2MHz	23a$	Spc	BD745F, BUW58, BUW73, 2SC2865(A)..
43879(R)	Si-Di	-	32a$/b&	RCA	D2406F(-R)
43880(R)	Si-Di	-	32a$/b&	RCA	D2406A(-R)
43881(R)	Si-Di	-	32a$/b&	RCA	D2406B(-R)
43882(R)	Si-Di	-	32a$/b&	RCA	D2406C(-R)
43883(R)	Si-Di	-	32a$/b&	RCA	D2406D(-R)
43884(R)	Si-Di	-	32a$/b&	RCA	D2406M(-R)
43889(R)	Si-Di	-	32a$/b&	RCA	D2412F(-R)
43890(R)	SI-Di	-	32a$/b&	RCA	D2412A(-R)
43891(R)	Si-Di	-	32a$/b&	RCA	D2412B(-R)
43892(R)	Si-Di	-	32a$/b&	RCA	D2412C(-R)
43893(R)	Si-Di	-	32a$/b&	RCA	D2412D(-R)
43894(R)	SI-Di	-	32a$/b&	RCA	D2412M(-R)
43899(R)	Si-Di	-	32a$/b&	RCA	D2520F(-R)
43900(R)	Si-Di	-	32a$/b&	RCA	D2520A(-R)
43901(R)	Si-Di	-	32a$/b&	RCA	D2520B(-R)
43902(R)	Si-Di	-	32a$/b&	RCA	D2520C(-R)
43903(R)	Si-Di	-	32a$/b&	RCA	D2520D(-R)
43904(R)	Si-Di	-	32a$/b&	RCA	D2520M(-R)
44001	Si-Di	-	31a	RCA	-
44002	Si-Di	-	31a	RCA	1N4002
44003	Si-Di	-	31a	RCA	1N4003
44004	Si-Di	-	31a	RCA	1N4004
44005	Si-Di	-	31a	RCA	1N4005
44006	Si-Di	-	31a	RCA	1N4006
44007	Si-Di	-	31a	RCA	1N4007
44933	Si-Di	-	31a	RCA	D2201F
44934	Si-Di	-	31a	RCA	D2201A

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44935	Si-Di	-	31a	RCA	D2201B
44936	Si-Di	-	31a	RCA	D2201D
44937	Si-Di	-	31a	RCA	D2201M
44938	Si-Di	-	31a	RCA	D2201N
45190	Si-NPN	AF,Sw-Pow,-/40V,7A,40W,>2MHz	17h$	Rca	(BD243A,BD543A,BD797,BD807,..)
45191	Si-NPN	=45190:-/60V	17h$	Rca	(BD243B,BD543B,BD799,BD809,..)
45192	Si-NPN	=45190:-/80V	17h$	Rca	(BD243C,BD543C,BD801,BD711,..)
45193	Si-PNP	AF,Sw-Pow,-/40V,7A,40W,>2MHz	17h$	Rca	(BD244A,BD544A,BD798,BD808,..)
45194	SI-PNP	=45193:-/60V	17h$	Rca	(BD244B,BD544B,BD800,BD810,..)
45195	Si-PNP	=45193:-/80V	17h$	Rca	(BD244C,BD544C,BD802,BD712,..)
45411	Diac	=D3202Y	-	Rca	→D3202Y
45412	Diac	=D3202U	-	Rca	→D3202U
4AA11	Si-PNP	4xPNP,-/60V,3A,2W,B>60	8-SIP	Rhm	-
4AA12	SI-P-Darl+Di	4xDarl,-/120V,6A,2W,B>2000	8-SIP	Rhm	-
4AC12	Si-N-Darl+Di	4xDarl,Z-Di,27V,2A,28W,B>7000	10-SIP	Hit	-
4AC13	Si-N-Darl+Di	4xDarl,Z-Di,50V,5A,28W,B>2000	10-SIP	Hit	-
4AC14	Si-N-Darl+Di	4xDarl,Z-Di,150V,5A,28W,B>1000	10-SIP	Hit	-
4AC15	Si-NPN	4xNPN,-/60V,3A,2W,B>60	10-SIP	Rhm	-
4AC16	Si-N-Darl+Di	4xDarl,Z-Di,-/60V,2A,2W,B>2000	10-SIP	Rhm	-
4AC17	Si-N-Darl+Di	4xDarl,Z-Di,-/60V,4A,2W,B>2000	10-SIP	Rhm	-
4AC18	Si-N-Darl+Di	4xDarl,-/100V,3A,2W,B>2000	10-SIP	Rhm	-
4AC19	Si-N-Darl+Di	4xDarl,-/200V,2,5A,2W,B>1000	10-SIP	Rhm	-
4AC20	Si-N-Darl+Di	4xDarl,-/100V,2A,2W,B>2000	10-SIP	Rhm	-
4AC21	Si-N-Darl+Di	4xDarl,Z-Di,-/72V,2A,2W,B>2000	10-SIP	Rhm	-
4AC22	Si-N-Darl+Di	4xDarl,Z-Di,-/100V,2A,2W,B>1000	10-SIP	Rhm	-
4AC23	Si-NPN-Darl	4xDarl,Z-Di,-/100V,3A,2W,B>1000	10-SIP	Rhm	-
4AC24	Si-NPN	4xNPN,Hi-beta,-/60V,3A,2W,B>600	10-SIP	Rhm	-
4AC25	Si-N-Darl+Di	4xDarl,Z-Di,-/60V,2A,2W,B>2000	10-SIP	Rhm	-
4AC26	Si-N-Darl+Di	4xDarl,Z-Di,-/100V,2A,2W,B>1000	10-SIP	Rhm	-
4AE11	Si-P/N-Darl	2xN-+2xP-Darl,300/300V,0,3A,32W	12-SIL	Hit	-
4AE12	Si-P/N	2xNPN+2xPNP,-/50V,3A,2W,B>60	10-SIP	Rhm	-
4AJ11	MOS-P-FET-e*	=4x2SJ173:8A,28W	12-SIP	Hit	-
4AK15	MOS-N-FET-e*	=4x2SK971:8A,28W	10-SIP	Hit	-
4AK16	MOS-N-FET-e	=4x2SK974:5A,28W	10-SIP	Hit	-
4AK17	MOS-N-FET-e*	=4x2SK972:10A,28W	10-SIP	Hit	-
4AK18	MOS-N-FET-e	=4x2SK973:2,5A,28W	10-SIP	Hit	-
4AK19	MOS-N-FET-e*	4xV-MOS,LogL,120V,5A,28W,<0,5Ω	10-SIP	Hit	-
4AK20	MOS-N-FET-e*	=4x2SK1300:5A,28W	10-SIP	Hit	-
4AK21	MOS-N-FET-e	=4x2SK1302:8A,28W	10-SIP	Hit	-
4AK22	MOS-N-FET-e*	=4x2SK1254:3A,28W	10-SIP	Hit	-
4AK23	MOS-N-FET-e*	=4x2SK1300:5A,32W	10-SIL	Hit	-
4AK25	MOS-N-FET-e	=4x2SK975:1,5A,24W	10-SIP	Hit	-
4AK26	MOS-N-FET-e*	=4x2SK972:10A,28W	12-SIP	Hit	-
4AK27	MOS-N-FET-e*	=4x2SK1949:5A,28W	10-SIP	Hit	-
4AK29	MOS-N-FET	4xV-MOS,LogL,60V,2A,28W,<0,35Ω	12-SIP	Rhm	-
4AM11	MOS-P/N-FET*	=2x2SJ172+2x2SK970:5A,28W	10-SIP	Hit	-
4AM12	MOS-P/N-FET*	=2x2SJ173+2x2SK971:8A,28W	10-SIP	Hit	-
4AM13	MOS-P/N-FET*	=2x2SJ182+2x2SK973:3A,28W	10-SIP	Hit	-
4AM14	MOS-P/N-FET*	=2x2SJ172+2x2SK970:8A,32W	12-SIL	Hit	-
4AM15	MOS-P/N-FET	=2x2SJ114+2x2SK400:4A,32W	12-SIL	Hit	-
4AM16	MOS-P/N-FET*	=2x2SJ172+2x2SK970:8A,28W	12-SIP	Hit	-
4AM17	MOS-P/N-FET*	=2x2SJ236+2x2SK1776:8A,28W	12-SIP	Hit	-
4E100-8	Trigger-Diode	=4E20-8:Ub=90..110V	31a	-	4E100M
4E100A	Trigger-Diode	=4E20A:Ub=80..120V	31a	-	4E100M
4E100M-8	Trigger-Diode	=4E20M-8:Ub=80..115V	31a	-	4E100A
4E200-8	Trigger-Diode	=4E20-8:Ub=180..220V	31a	-	4E200M
4E200A	Trigger-Diode	=4E20A:Ub=170..230V	31a	-	4E200M
4E200M-8	Trigger-Diode	=4E20M-8:Ub=160..230V	31a	-	4E200A
4E20-8	Trigger-Diode	Ub=16..24V,μS<125?A,Itsm=5A	31a	Itt	4E20M
4E20A	Trigger-Diode	Ub=14..26V,Itsm=5A	31a	Itt	4E20M
4E20M-8	Trigger-Diode	Ub=14..25V,Itsm=5A	31a	Itt	4E20A
4E30-8	Trigger-Diode	=4E20-8:Ub=26..34V	31a	-	4E30M
4E30A	Trigger-Diode	=4E20A:Ub=24..36V	31a	-	4E30M
4E30M-8	Trigger-Diode	=4E20M-8:Ub=23..36V	31a	-	4E30A

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4E40-8	Trigger-Diode	=4E20-8: Ub=36..44V	31a	-	4E40M
4E40A	Trigger-Diode	=4E20A: Ub=34..46V	31a	-	4E40M
4E40M-8	Trigger-Diode	=4E20M-8: Ub=32..46V	31a	-	4E40A
4E50-8	Trigger-Diode	=4E20-8: Ub=46..54V	31a	-	4E50M
4E50A	Trigger-Diode	=4E20A: Ub=44..56V	31a	-	4E50M
4E50M-8	Trigger-Diode	=4E20M-8: Ub=41..57V	31a	-	4E50A
4EX580	Trigger-Diode	Ub=15..25V, µS<0,25mA, Itsm=5A	31a	Itt	4E20M
4EX581	Trigger-Diode	=4EX580: Ub=25..35V	31a	-	4E30M
4EX582	Trigger-Diode	=4EX580: Ub=35..50V	31a	-	4E40M
4GZ..R	Z-Di	=4GZ..:	32b&	Ssc	BZX98/..R, BZY93/..R
4GZ10A..82A	Z-Di	10..82V, 10%, 4W(Tc=75°)	32a$	Ssc	BZX98/..BZY93/..
4GZ10B..18B	Z-Di	100..180V, 10%, 4W(Tc=75°)	32a$	Ssc	BZX98/..
4J100-5	Trigger-Diode	=4J50-5: Ub=90..110V	34a	-	4E100M
4J200-5	Trigger-Diode	=4J50-5: Ub=180..220V	34a	-	4E200M
4J50-5	Trigger-Diode	Ub=45..55V, µS<0,25mA	34a	Itt	4E50M
5					
504BSY	N-FET	=BSV78	2b	Phi	→BSV78
508BSY	MOS-N-FET-d	=BSV81	5m+	Phi	→BSV81
52530A	Si-NPN	?BU326A	23a$	-	→BU326A
528BSY	MOS-N-FET-e	?2N4351	5m+	Phi	→2N4351
555BRY	PUT	=BRY61	35b	Phi	→BRY61
556BCYA	Si-PNP	=BCX17	35a	Phi	→BCX17
556BCYB	Si-PNP	=BCX18	35a	Phi	→BCX18
557BCYA	Si-NPN	=BCX19	35a	Phi	→BCX19
557BCYB	Si-NPN	=BCX20	35a	Phi	→BCX20
5609	Si-NPN	→CS5609	-		-
5610	Si-PNP	→CS5610	-		-
563BSY	Si-PNP	=BSS63	35a	Phi	→BSS63
564BSY	Si-NPN	=BSS64	35a	Phi	→BSS64
565BAT	Si-Di	-	35e	Philips	BAT17
574BAT	Si-Di	-	35e	Philips	BAT18
5AE11	Si-P/N-Darl	4xNPN+1xPNP-Darl, -/80V, 2A, 2W	12-SIP	Rhm	-
5DL2C41A	Si-Di	-	17p	Toshiba	MUR620
5DL2C48A	Si-Di	-	30p	Toshiba	U5DL2C48A
5DL2CZ47A	Si-Di	-	17p	Toshiba	MA649, MA6S3, MA693
5DLZ47A	Si-Di	-	17d	Toshiba	MA690, BYW29-200F
5EZ3,6..200D5..10	Z-Di	3,6..200V, 5W, D5=5%, D10=10%	31a	Sie	BZV40/..BZV48/..1N5334..5388
5FL2C48A	Si-Di	-	30p	Toshiba	U5FL2C48A
5FL2CZ47A	Si-Di	-	17p	Toshiba	MA6S3, MA693
5FWJ2C48M	Si-Di	-	30p	Toshiba	U5FWJ2C48M
5FWJ2CZ47M	Si-Di	-	17p	Toshiba	MA749(A)
5GL2CZ47	Si-Di	-	17p	Toshiba	-
5GL2CZ47A	Si-Di	-	17p	Toshiba	MA693
5GLZ47A	Si-Di	-	17d	Toshiba	BYR29F-600
5GUZ47	Si-Di	-	17d	Toshiba	BYR29F-600
5GWJ2C42	Si-Di	-	17p	Toshiba	BYV18-40, BYV118-40
5GWJ2C48C	Si-Di	-	30p	Toshiba	U5GWJ2C48C
5GWJ2CZ47C	Si-Di	-	17p	Toshiba	MA749(A)
5GWJZ47	Si-Di	-	17d	Toshiba	MA2D749
5JLZ47	Si-Di	-	17d	Toshiba	BYR29F-600
5JUZ47	Si-Di	-	17d	Toshiba	BYR29F-600
5KP5.0..110(A)	Z-Di/TVS	TAZ, 5..110V, 5W, Pbr=5kW(1µS)	31a	Gie,Fag	BZW11/..1N5629..58, 1N6267..96
5P0SM	Thy-50Hz	=5P1M: 50V	17h$	Nec	T3,5N..TAG661-..TAG662-..
5P1M	Thy-50Hz	100V, 5A(Tc=103°C), Igt/Ih<15/<10mA	17h$	Nec	T3,5N..TAG661-..TAG662-..
5P2M	Thy-50Hz	=5P1M: 200V	17h$	Nec	T3,5N..TAG661-..TAG662-..
5P4J(Z)	Thy-50Hz	400V, 5A(Tc=95°C), Igt/Ih<0,2/=1mA	30h$	Nec	-
5P4M	Thy-50Hz	=5P1M: 400V	17h$	Nec	T3,5N..TAG661-..TAG662-..
5P5M	Thy-50Hz	=5P1M: 500V	17h$	Nec	T3,5N..TAG661-..TAG662-..
5P6J(Z)	Thy-50Hz	=5P4J: 600V	30h$	Nec	-
5P6M	Thy-50Hz	=5P1M: 600V	17h$	Nec	T3,5N..TAG661-..TAG662-..
5S4M	Thy-Fast	400V, 5A(Tc=83°C), Igt<50/60mA, <5µS	17h$	Nec	BT151/500, TAG655S-400, TAG656S-400
5THZS2	Si-DI	-	18d	Toshiba	-
5TUZ47	Si-Di	-	17d	Toshiba	DTV32F

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5TUZ47C	Si-Di	-	17d	Toshiba	DTV32F
5TUZ52	Si-Di	-	18d	Toshiba	-
5TUZ52C	Si-Di	-	18d	Toshiba	-
5VUZ52C	Si-Di	-	18d	Toshiba	-
6					
60024	Si-NPN	?2N3055	-	Rca	→2N3055
60911	Thy-Fast	?S3703SF	22a$	Rca	→S3703SF
60912	Thy-Fast	?S3702S	22a$	Rca	→S3702S
60A..Y	Thy	=TAG60A..Y	7a	Tag	→TAG60A..Y
636BC/A	Si-PNP	=BCX51	39b	Phi	→BCX51
636BC/B	Si-PNP	=BCX52	39b	Phi	→BCX52
636BC/C	Si-PNP	=BCX53	39b	Phi	→BCX53
637BC/A	Si-NPN	=BCX54	39b	Phi	→BCX54
637BC/B	Si-NPN	=BCX55	39b	Phi	→BCX55
637BC/C	Si-NPN	=BCX56	39b	Phi	→BCX56
6AM11	MOS-P/N-FET* ..	=3x2SJ172+3x2SK970:5A,36W	12-SIP	Hit	-
6AM12	MOS-P/N-FET* ..	=3x2SJ172+3x2SK970:7A,42W	12-SIL	Hit	-
6AM13	MOS-P/N-FET* ..	=3x2SJ173+3x2SK971:10A,42W	12-SIL	Hit	-
6AM14	MOS-P/N-FET* ..	3xP+3xNV-MOS,LogL,60V,7A,42W	12-SIL	Hit	-
7					
70HF-10..-100	Si-Di	-	32a$	Motorola	DS75-..
70HF-10R..100R	Si-Di	-	32b&	-	-
71T2	Si-NPN	AF,Sw-Pow,80V,2A,15W,50MHz,B>30	43a$	STE	(BD379,2SC3252,2SD1177..1178,..)
72T2	Si-NPN	=71T2:B>75	43a$	STE	(BD379,2SC3252,2SD1177..1178,..)
73T2	Si-NPN	AF,Sw-Pow,80V,1A,15W,B>30	43a$	STE	(BD139,BD230,BD379,2SC3252,..)
74ACT715..	TTL-IC	=LM1882	-	Nsc	→LM1882
74AHC1G00	CMOS-Logic	2-input NAND gate	SOT-353	Phi	-
74AHC1G02	CMOS-Logic	2-input NOR gate	SOT-353	Phi	-
74AHC1G04	CMOS-Logic	Inverter	SOT-353	Phi	-
74AHC1G06GW	CMOS-Logic	Inverter (Open drain output)	SOT-353	Phi	-
74AHC1G07GV	CMOS-Logic	Noninverting buffer (Open drain output)	SOT-753	Phi	-
74AHC1G07GW	CMOS-Logic	Noninverting buffer (Open drain output)	SOT-353	Phi	-
74AHC1G08	CMOS-Logic	2-input AND gate	SOT-353	Phi	-
74AHC1G125	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74AHC1G126	CMOS-Logic	Noninverting 3-State Buffer/CMOS LLS	SOT-353	Phi	-
74AHC1G14	CMOS-Logic	Inverting Schmitt-trigger	SOT-353	Phi	-
74AHC1G32	CMOS-Logic	2-input OR gate	SOT-353	Phi	-
74AHC1G66GW	CMOS-Logic	Bilateral analogic switch	SOT-353	Phi	-
74AHC1G79GV	CMOS-Logic	Single D-type flip-flop	SOT-753	Phi	-
74AHC1G79GW	CMOS-Logic	Single D-type flip-flop	SOT-353	Phi	-
74AHC1G86	CMOS-Logic	2-input EXCLUSIVE OR gate	SOT-353	Phi	-
74AHC1GU04	CMOS-Logic	Inverter	SC-88A	Phi	-
74AHCT1G00	CMOS-Logic	2-input NAND gate	SOT-353	Phi	-
74AHCT1G02	CMOS-Logic	2-input NOR gate	SOT-353	Phi	-
74AHCT1G04	CMOS-Logic	Inverter	SOT-353	Phi	-
74AHCT1G06GW	CMOS-Logic	Inverter (Open drain output)	SOT-353	Phi	-
74AHCT1G07GV	CMOS-Logic	Noninverting buffer (Open drain output)	SOT-753	Phi	-
74AHCT1G07GW	CMOS-Logic	Noninverting buffer (Open drain output)	SOT-353	Phi	-
74AHCT1G08	CMOS-Logic	2-input AND gate	SOT-353	Phi	-
74AHCT1G125	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74AHCT1G126	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74AHCT1G14	CMOS-Logic	Inverting Schmitt-trigger	SOT-353	Phi	-
74AHCT1G32	CMOS-Logic	2-input OR gate	SOT-353	Phi	-
74AHCT1G66GW	CMOS-Logic	Bilateral analogic switch	SOT-353	Phi	-
74AHCT1G79GV	CMOS-Logic	Single D-type flip-flop	SOT-753	Phi	-
74AHCT1G79GW	CMOS-Logic	Single D-type flip-flop	SOT-353	Phi	-
74AHCT1G86	CMOS-Logic	2-input EXCLUSIVE OR gate	SOT-353	Phi	-
74AHCT1GU04	CMOS-Logic	Inverter	SOT-353	Phi	-
74HC1G00	CMOS-Logic	2-input NAND gate	SOT-353	Phi	-
74HC1G02	CMOS-Logic	2-input NOR gate	SOT-353	Phi	-
74HC1G04	CMOS-Logic	Inverter	SOT-353	Phi	-
74HC1G08	CMOS-Logic	2-input AND gate	SOT-353	Phi	-

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74HC1G125	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74HC1G126	CMOS-Logic	Noninverting 3-State Buffer/CMOS LLS	SOT-353	Phi	-
74HC1G14	CMOS-Logic	Inverting Schmitt-trigger	SOT-353	Phi	-
74HC1G32	CMOS-Logic	2-input OR gate	SOT-353	Phi	-
74HC1G66GW	CMOS-Logic	Bilateral analogic switch	SOT-353	Phi	-
74HC1G86	CMOS-Logic	2-input EXCLUSIVE OR gate	SOT-353	Phi	-
74HC1GU04	CMOS-Logic	Inverter	SOT-353	Phi	-
74HCT1G00	CMOS-Logic	2-input NAND gate	SOT-353	Phi	-
74HCT1G02	CMOS-Logic	2-input NOR gate	SOT-353	Phi	-
74HCT1G04	CMOS-Logic	Inverter	SOT-353	Phi	-
74HCT1G08	CMOS-Logic	2-input AND gate	SOT-353	Phi	-
74HCT1G125	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74HCT1G126	CMOS-Logic	Noninverting 3-State Buffer	SOT-353	Phi	-
74HCT1G14	CMOS-Logic	Inverting Schmitt-trigger	SOT-353	Phi	-
74HCT1G32	CMOS-Logic	2-input OR gate	SOT-353	Phi	-
74HCT1G66GW	CMOS-Logic	Bilateral analogic switch	SOT-353	Phi	-
74HCT1G86	CMOS-Logic	2-input EXCLUSIVE OR gate	SOT-353	Phi	-
74HCT1GU04	CMOS-Logic	Inverter	SOT-353	Phi	-
74LV4799D	Lin-IC	=74LV4799N: SMD	16-MDIP	-	-
74LV4799N	Lin-IC	Timer for NiCd & NiMH Chargers	16-DIP	Phi	-
74T2	Si-NPN	=73T2: B>75	43a$	STE	(BD139, BD230, BD379, 2SC3252,..)
8					
8003BBB	Si-NPN	?BF337	-		→BF337
8050	Si-NPN	=SS8050	-		→SS8050
80C31..C782	CMOS-µC-IC	8-bit Single Chip Microcontroller, I²C-bus	-	Phi	-
83C053:.	CMOS-µC-IC	TV Microcontr., 8192x8-bit mµSk. ROM	42-DIP	Phi	-
83C054..	CMOS-µC-IC	TV Microcontr., 16384x8-bit mµSk. ROM	42-DIP	Phi	-
83C528..C654	CMOS-µC-IC	TV, 8-bit Single Chip Microcontroller, EPROM, I²C-bus-Bus	-	Phi	-
84C44..	CMOS-µC-IC	8-bit, Volt. Synth. Tuning, OSD, I²C-bus	42-SDIP	Phi	-
84C64..	CMOS-µC-IC	8-bit, Volt. Synth. Tuning, OSD, I²C-bus	42-SDIP	Phi	-
84C84..	CMOS-µC-IC	8-bit, Volt. Synth. Tuning, OSD, I²C-bus	42-SDIP	Phi	-
8550	Si-PNP	=SS8550	-		→SS8550
87C054..	CMOS-µC-IC	TV Microcontr., 16384x8-bit EPROM, I²C-bus	42-DIP	Phi	-
896	Se-Diode	→AEG896	31a	Aeg	-
8P1M	Thy-50Hz	100V, 8A(Tc=90°C), Igt/Ih<15/<10mA	17h$	Nec	TIC122..TIC126..T7,5N..
8P2M	Thy-50Hz	=8P1M: 200V	17h$	-	TIC122..TIC126..T7,5N..
8P4J(Z)	Thy-50Hz	400V, 8A(Tc=75°C), Igt/Ih<10/=6mA	30h$	Nec	-
9					
9003	Si-NPN	→CS9003	7e	-	-
9010	Si-NPN	→CS9010	7e	-	-
9011	Si-NPN	=SS9011	7e	-	→SS9011
9012(HH)	Si-PNP	=SS9012	7e	-	→SS9012
9013(HH)	Si-NPN	=SS9013	7e	-	→SS9013
9014	Si-NPN	=SS9014	7e	-	→SS9014
9015	Si-PNP	=SS9015	7e	-	→SS9015
9016	SI-NPN	=SS9016	7e	-	→SS9016
9017	Si-NPN	→CS9017	7e	-	-
9018	Si-NPN	=SS9018	7e	-	→SS9018
9020	Si-PNP	→CS9020	7e	-	-
9021	Si-NPN	→CS9021	7e	-	-
9022	Si-NPN	→CS9022	7e	-	-
90T2	Si-NPN	=2N1990: 0,2W	7c	STE	BC639, 2N3700..01, 2SD667, 2SD774..
92GE37A..C	Si-NPN	=2N6705..6707	30c	Gen	→2N6705..6707
92GE487	Si-NPN	=2N6711	30c	Gen	→2N6711
92GE488	Si-NPN	=2N6712	30c	Gen	→2N6712
92GE489	Si-NPN	=2N6713	30c	Gen	→2N6713
92GE77A..C	Si-PNP	=2N6708..6710	30c	Gen	→2N6708..6710
92GU01	Si-NPN	=2N6714	30e	Gen	→2N6714
92GU01A	Si-NPN	=2N6715	30e	Gen	→2N6715
92GU05	Si-NPN	=2N6716	30e	Gen	→2N6716
92GU06	Si-NPN	=2N6717	30e	Gen	→2N6717
92GU10	Si-NPN	=2N6719	30e	Gen	→2N6719

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92GU391	Si-NPN	=2N6733	30e	Gen	→2N6733
92GU392	Si-NPN	=2N6734	30e	Gen	→2N6734
92GU393	Si-NPN	=2N6735	30e	Gen	→2N6735
92GU45	Si-NPN	=2N6724	30e	Gen	→2N6724
92GU45A	Si-NPN	=2N6725	30e	Gen	→2N6725
92GU51	Si-PNP	=2N6726	30e	Gen	→2N6726
92GU51A	Si-PNP	=2N6727	30e	Gen	→2N6727
92GU55	Si-PNP	=2N6728	30e	Gen	→2N6728
92GU56	Si-PNP	=2N6729	30e	Gen	→2N6729
92PE37A	Si-NPN	GenP,60/45V,?1A,0,85W,>50MHz	30c	Nsc	(BD517,BD525,2SD1281..1284,..)
92PE37B	Si-NPN	=92PE37A:80/60V	30c	-	(BD519,BD527,2SD1281..1284,..)
92PE37C	Si-NPN	=92PE37A:100/80V	30c	-	(BD519,BD529,2SD1281..1284,..)
92PE487	Si-NPN	Vid,160/160V,?0,03A,0,85W	30c	Nsc	(BF615,BF617,BF757..759,..)
92PE488	Si-NPN	=92PE487:250/250V	30c	-	(BF615,BF617,BF757..759,..)
92PE489	Si-NPN	=92PE487:300/300V	30c	-	(BF617,BF758..759,MPSU10,..)
92PE77A	Si-PNP	GenP,60/45V,1A,0,85W,>50MHz	30c	Nsc	(BD518,BD526,2SB957..960,..)
92PE77B	Si-PNP	=92PE77A:80/60V	30c	-	(BD520,BD528,2SB957..960,..)
92PE77C	Si-PNP	=92PE77A:100/80V	30c	-	(BD520,BD530,2SB957..960,..)
92PU01	Si-NPN	GenP,40/30V,2A,0,85W,>100MHz	30e	Nsc,Mic	(BD507,BD515,BD525,2SD1801,..)
92PU01A	Si-NPN	=92PU01:50/40V	30e	-	(BD509,BD515,BD525,2SD1801,..)
92PU02	Si-NPN	GenP,-/40V,0,8A,0,85W,>150MHz	30e	Mic	(BD515,BD525,2SD1074..75,2SD1733..)
92PU05	Si-NPN	GenP,-/60V,2A,0,85W,>50MHz	30e	Nsc,Mic	(BD527,BD529,2SC4135,2SD1281..82..)
92PU06	Si-NPN	GenP,-/80V,2A,0,85W,>50MHz	30e	Nsc,Mic	(BD527,BD529,2SC4135,2SD1281..82..)
92PU07	Si-NPN	GenP,-/80V,2A,0,85W,>50MHz	30e	Nsc,Mic	(BD527,BD529,2SC4135,2SD1281..82..)
92PU10	Si-NPN	Vid,-/300V,0,5A,0,85W	30e	Nsc,Mic	(BF462,BF758..759,MPSU10,..)
92PU100	Si-NPN	GenP,100/80V,?1A,0,85W,>50MHz	30e	Nsc	(BD529,2SD1074..75,2SD1281..84,..)
92PU200	Si-PNP	GenP,100/80V,?1A,0,85W,>50MHz	30e	Nsc	(BD530,2SB844..845,2SB957..960,..)
92PU36	Si-NPN	AF/Vid,175/150V,?0,5A,0,85W	30e	Nsc	(BF466..468,BF666..668,BF757..759+)
92PU36A	Si-NPN	=92PU36:225/200V	30e	-	(BF467..468,BF667..668,BF757..759+)
92PU36B	Si-NPN	=92PU36:275/250V	30e	-	(BF468,BF668,BF758..759,..)
92PU36C	Si-NPN	=92PU36:325/300V	30e	-	(BF462,BF759)
92PU391	Si-NPN	Vid,200/200V,0,85W,>50MHz	30e	Nsc	(BF615,BF617,BF757..759,MPSU10..)
92PU392	Si-NPN	=92PU391:250/250V	30e	Nsc	(BF615,BF617,BF757..759,MPSU10..)
92PU393	Si-NPN	=92PU391:300/300V	30e	Nsc	(BF617,BF758..759,MPSU10,..)
92PU45	Si-NPN-Darl	GenP,50V,2A,0,85W,>100MHz,B>25000	30e	Nsc,Mic	-
92PU45A	Si-NPN-Darl	=92PU45:60V	30e	-	-
92PU51	Si-PNP	GenP,40/30V,2A,0,85W,>50MHz	30e	Nsc,Mic	(BD508,BD516,BD526,2SB1201,..)
92PU51A	Si-PNP	=92PU51:50/40V	30e	-	(BD510,BD516,BD526,2SB1201,..)
92PU52	Si-PNP	GenP,-/40V,0,8A,0,85W,>150MHz	30e	Mic	(BD516,BD526,2SB844..45,2SB1181..)
92PU55	Si-PNP	GenP,-/60V,2A,0,85W,>50MHz	30e	Nsc,Mic	(BD528,BD530,2SA1593,2SB957..58..)
92PU56	Si-PNP	=92PU56:-/80V	30e	Nsc,Mic	(BD528,BD530,2SA1593,2SB957..58..)
92PU57	Si-PNP	=92PU56:-/100V	30e	Nsc,Mic	(BD530,2SA1593,2SB957..58,..)
92PU60	Si-PNP	Vid,-/300V,0,5A,0,85W,>50MHz	30e	Mic	(BF465,BF761..762,MPSU60,..)
92PU95	Si-PNP-Darl	GenP,40V,2A,0,85W,>50MHz,B>15000	30e	Mic	-
9400	Si-NPN	AF-Driver,50V,0,8A,0,625W,100MHz	-		→BC337
9665	Lin-IC	=ULN2001A	16-DIP	Mot	MC1411,ULN2001A
9666	Lin-IC	=ULN2002A	16-DIP	Mot	MC1412,ULN2002A
9667	Lin-IC	=ULN2003A	16-DIP	Mot	MC1413,ULN2003A
9668	Lin-IC	=ULN2004A	16-DIP	Mot	MC1416,ULN2004A
972	Se-Diode	→AEG972	31a	Aeg	-
992	Se-Diode	→AEG992	31a	Aeg	-
()					
(-1,T4)	Triac	DCM=600V,DCN=800V	-		-
(2)GA109	Ge-Di	FM-Dem,50V,0,015A	31a	Hfo	AA113,1N34,1N54,1N60
(2)GA113	Ge-Di	Dem,Diskr,35V,0,03A(ss)	31a	Hfo	AA113,AA119,1N34,1N54,1N60
(2)OA646	Ge-Di	=GA109	31a	Hfo	→GA109
(4)GA114	Ge-Di	4xGe-Di,Ring-Dem,35V,0,03A(ss)	31a	Hfo	→4xGA113
(AEG)1006	Se-Di	1600/1700V,2,3mA	31a	-	E800C2,3
(AEG)896	Se-Di	880/950V,3,3mA	31a	-	E400C3,3
(AEG)972	Se-Di	1100/1200V,3mA	31a	-	ES00C3
(AEG)992	Se-Di	1300/1450V,2,7mA	31a	-	E600C2,7
(NT)0100(ECO)	Si-Di	Uni,75V,0,125A	2c	Ntn	BA157..159,BAY19..21,BAY87..89,+
(NT)0101(ECO)	Si-Di	=(NT)0100(ECO):150V	2c	Ntn	BA157..159,BAY20..21,BAY88..89,+

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(NT)0102(EC0)	Si-Di	=(NT)0100(EC0):300V	2c	Ntn	BA157..159,BAY21,BAY88..89,+
(NT)0110(EC0)	Si-Di	=(NT)0100(EC0)	2c	Ntn	BA157..159,BAY19..21,BAY87..89,+
(NT)0111(EC0)	Si-Di	=(NT)0100(EC0):150V	2c	Ntn	BA157..159,BAY20..21,BAY88..89,+
(NT)0112(EC0)	Si-Di	=(NT)0100(EC0):300V	2c	Ntn	BA157..159,BAY21,BAY88..89,+
(NT)0114(EC0)	Si-Di	=(NT)0100(EC0):500V	2c	Ntn	BA158..159,BA199/550,BAY89..91,+
(NT)0241(EC0)	Si-Di	GI-L,100V,3A(Tc=100o)	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)0241..48R(EC0)	Si-Di	=(NT)0241..0248(EC0):800V	32a$	Ntn	BYX38/..,BYX39/..
(NT)0242(EC0)	Si-Di	=(NT)0241(EC0):200V	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)0243(EC0)	Si-Di	=(NT)0241(EC0):300V	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)0245(EC0)	Si-Di	=(NT)0241(EC0):500V	32b&	Ntn	BYX38/600R,BYX39/600R
(NT)0248(EC0)	Si-Di	=(NT)0241(EC0):800V	32b&	Ntn	BYX38/900R,BYX39/800R
(NT)0300(EC0)	Si-Di	GI,75V,0,75A	31a	Ntn	BY126..127,BY133..135,1N4002..07,+
(NT)0301(EC0)	Si-Di	=(NT)0300(EC0):150V	31a	Ntn	BY126..127,BY133..135,1N4003..07,+
(NT)0302(EC0)	Si-Di	=(NT)0300(EC0):300V	31a	Ntn	BY126..127,BY133..134,1N4004..07,+
(NT)0304(EC0)	Si-Di	=(NT)0300(EC0):500V	31a	Ntn	BY126..127,BY133..134,1N4005..07,+
(NT)0307(EC0)	Si-Di	=(NT)0300(EC0):800V	31a	Ntn	BY127,BY133,BY227,1N4006..07,+
(NT)0310(EC0)	Si-Di	=(NT)0300(EC0)	31a	Ntn	BY126..127,BY133..135,1N4002..07,+
(NT)0311(EC0)	Si-Di	=(NT)0300(EC0):150V	31a	Ntn	BY126..127,BY133..135,1N4003..07,+
(NT)0312(EC0)	Si-Di	=(NT)0300(EC0):300V	31a	Ntn	BY126..127,BY133..134,1N4004..07,+
(NT)0314(EC0)	Si-Di	=(NT)0300(EC0):500V	31a	Ntn	BY126..127,BY133..134,1N4005..07,+
(NT)0317(EC0)	Si-Di	=(NT)0300(EC0):800V	31a	Ntn	BY127,BY133,BY227,1N4006..07,+
(NT)0320(EC0)	Si-Di	=(NT)0300(EC0)	31a	Ntn	BY126..127,BY133..135,1N4002..07,+
(NT)0321(EC0)	Si-Di	=(NT)0300(EC0):150V	31a	Ntn	BY126..127,BY133..135,1N4003..07,+
(NT)0322(EC0)	Si-Di	=(NT)0300(EC0):300V	31a	Ntn	BY126..127,BY133..134,1N4004..07,+
(NT)0324(EC0)	Si-Di	=(NT)0300(EC0):500V	31a	Ntn	BY126..127,BY133..134,1N4005..07,+
(NT)0327(EC0)	Si-Di	=(NT)0300(EC0):800V	31a	Ntn	BY127,BY133,BY227,1N4006..07,+
(NT)0400(EC0)	Si-Di	Uni,75V,0,25A	31a	Ntn	BA157..159,BA199/250,BAY19..21,+
(NT)0401(EC0)	Si-Di	=(NT)0400(EC0):150V	31a	Ntn	BA157..159,BA199/250,BAY20..21,+
(NT)0402(EC0)	Si-Di	=(NT)0400(EC0):300V	31a	Ntn	BA157..159,BA199/350,BAY21,+
(NT)0404(EC0)	Si-Di	=(NT)0400(EC0):500V	31a	Ntn	BA158..159,BA199/550,BAY89..91,+
(NT)0410(EC0)	Si-Di	=(NT)0400(EC0)	31a	Ntn	BA157..159,BA199/250,BAY19..21,+
(NT)0411(EC0)	Si-Di	=(NT)0400(EC0):150V	31a	Ntn	BA157..159,BA199/250,BAY20..21,+
(NT)0412(EC0)	Si-Di	=(NT)0400(EC0):300V	31a	Ntn	BA157..159,BA199/350,BAY21,+
(NT)0414(EC0)	Si-Di	=(NT)0400(EC0):500V	31a	Ntn	BA158..159,BA199/550,BAY89..91,+
(NT)0500(EC0)	Si-Di	Uni,75V,0,25A	31a	Ntn	BA157..159,BA199/250,BAY19..21,+
(NT)0501(EC0)	Si-Di	=(NT)0500(EC0):150V	31a	Ntn	BA157..159,BA199/250,BAY20..21,+
(NT)0502(EC0)	Si-Di	=(NT)0500(EC0):300V	31a	Ntn	BA157..159,BA199/350,BAY21,+
(NT)0503(EC0)	Si-Di	=(NT)0500(EC0):400V	31a	Ntn	BA157..159,BA199/550,BAY89..91,+
(NT)0504(EC0)	Si-Di	=(NT)0500(EC0):500V	31a	Ntn	BA158..159,BA199/550,BAY89..91,+
(NT)0507(EC0)	Si-Di	=(NT)0500(EC0):800V	31a	Ntn	BA159,BAY90..91,BY204/8,+
(NT)0601(EC0)	Si-Di	GI-L,200V,17,5A(Tc=100o)	32b&	Ntn	BYX25/600R,SSiE2040
(NT)0601..08R(EC0)	Si-Di	=(NT)0601..0608(EC0):	32a$	Ntn	BYX25/..
(NT)0602(EC0)	Si-Di	=(NT)0601(EC0):300V	32b&	Ntn	BYX25/600R,SSiE2040
(NT)0604(EC0)	Si-Di	=(NT)0601(EC0):600V	32b&	Ntn	BYX25/600R,SSiE2040
(NT)0606(EC0)	Si-Di	=(NT)0601(EC0):900V	32b&	Ntn	BYX25/1000R,SSiE2060
(NT)0608(EC0)	Si-Di	=(NT)0601(EC0):1200V	32b&	Ntn	BYX25/1200R,SSiE2080
(NT)0612(EC0)	Si-Di	GI-L,300V,40A(Tc=100o)	73b&	Ntn	D60/400,DS42-04A
(NT)0614(EC0)	Si-Di	=(NT)0612(EC0):600V	73b&	Ntn	D60/800,DS42-07A
(NT)0616(EC0)	Si-Di	=(NT)0612(EC0):900V	73b&	Ntn	D60/1200,DS42-11A
(NT)0618(EC0)	Si-Di	=(NT)0612(EC0):1200V	73b&	Ntn	D60/1200,DS42-14A
(NT)0619(EC0)	Si-Di	=(NT)0612(EC0):1500V	73b&	Ntn	D60/1600,DS42-16A
(NT)0622(EC0)	Si-Di	GI-L,300V,100A(Tc=100o)	73b&	Ntn	D160/400,DS85-04C
(NT)0624(EC0)	Si-Di	=(NT)0622(EC0):600V	73b&	Ntn	D160/800,DS85-06C
(NT)0626(EC0)	Si-Di	=(NT)0622(EC0):900V	73b&	Ntn	D160/1200,DS85-10C
(NT)0628(EC0)	Si-Di	=(NT)0622(EC0):1200V	73b&	Ntn	D160/1200,DS85-12C
(NT)0629(EC0)	Si-Di	=(NT)0622(EC0):1500V	73b&	Ntn	D160/1600,DS85-16C
(NT)0632(EC0)	Si-Di	GI-L,300V,20A(Tc=100o)	73b&	Ntn	D21S/1000,D24/400
(NT)0634(EC0)	Si-Di	=(NT)0632(EC0):600V	73b&	Ntn	D21S/1000,D24/800
(NT)0636(EC0)	Si-Di	=(NT)0632(EC0):900V	73b&	Ntn	D21S/1000,D24/1200
(NT)0638(EC0)	Si-Di	=(NT)0632(EC0):1200V	73b&	Ntn	D21S/1200,D24/1200
(NT)0639(EC0)	Si-Di	=(NT)0632(EC0):1500V	73b&	Ntn	D24/1600
(NT)0700(EC0)	Si-Di	?1N4002	31a	Ntn	→1N4002
(NT)0701(EC0)	Si-Di	?1N4003	31a	Ntn	→1N4003
(NT)0702(EC0)	Si-Di	?1N4004	31a	Ntn	→1N4004

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(NT)0704(EC0)	Si-Di	?1N4005	31a	Ntn	→1N4005
(NT)0707(EC0)	Si-Di	?1N4006	31a	Ntn	→1N4006
(NT)0708(EC0)	Si-Di	?1N4007	31a	Ntn	→1N4007
(NT)0710(EC0)	Si-Di	?1N4001	31a	Ntn	→1N4001
(NT)0771(EC0)	Si-Di	GI,Uni,150V,1,5A	31a	Ntn	BY226..227,BY251..255,1N5393..99,+
(NT)0772(EC0)	Si-Di	=(NT)0771(EC0):300V	31a	Ntn	BY226..227,BY252..255,1N5394..99,+
(NT)0774(EC0)	Si-Di	=(NT)0771(EC0):500V	31a	Ntn	BY226..227,BY253..255,1N5397..99,+
(NT)0776(EC0)	Si-Di	=(NT)0771(EC0):800V	31a	Ntn	BY227,BY254..255,1N5398..99,+
(NT)0778(EC0)	Si-Di	=(NT)0771(EC0):1000V	31a	Ntn	BY227,BY228,BY255,1N5399,+
(NT)0779(EC0)	Si-Di	=(NT)0771(EC0):1200V	31a	Ntn	BY227,BY228,BY255,BYX87,+
(NT)0952(EC0)	Si-Di	kV-GI,1kV,0,6A	-	Ntn	-
(NT)0953(EC0)	Si-Di	=(NT)0952(EC0):1,5kV	-	Ntn	-
(NT)0954(EC0)	Si-Di	=(NT)0952(EC0):2kV	-	Ntn	-
(NT)0955(EC0)	Si-Di	=(NT)0952(EC0):2,5kV	-	Ntn	-
(NT)0956(EC0)	Si-Di	=(NT)0952(EC0):3kV	-	Ntn	-
(NT)0957(EC0)	Si-Di	=(NT)0952(EC0):3,5kV	-	Ntn	-
(NT)0958(EC0)	Si-Di	=(NT)0952(EC0):4kV	-	Ntn	-
(NT)1005..33(EC0)	Z-Di	→(NT)1105..1133(EC0)	-	Ntn	-
(NT)1101(c)(EC0)	Z-Di	2,7V,0,25W,10%(c=5%)	2c	Ntn	BZX55/..,BZX79/..,ZPD..,1N4682..4714+
(NT)1102(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):3,3V	2c	Ntn	-
(NT)1103(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):3,9V	2c	Ntn	-
(NT)1104(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):4,7V	2c	Ntn	-
(NT)1105(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):5,6V	2c	Ntn	-
(NT)1106(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):6,8V	2c	Ntn	-
(NT)1107(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):7,5V	2c	Ntn	-
(NT)1108(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):8,2V	2c	Ntn	-
(NT)1109(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):9,1V	2c	Ntn	-
(NT)1110(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):10V	2c	Ntn	-
(NT)1111(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):11V	2c	Ntn	-
(NT)1112(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):12V	2c	Ntn	-
(NT)1113(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):13V	2c	Ntn	-
(NT)1115(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):15V	2c	Ntn	-
(NT)1116(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):16V	2c	Ntn	-
(NT)1118(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):18V	2c	Ntn	-
(NT)1120(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):20V	2c	Ntn	-
(NT)1122(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):22V	2c	Ntn	-
(NT)1124(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):24V	2c	Ntn	-
(NT)1127(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):27V	2c	Ntn	-
(NT)1130(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):30V	2c	Ntn	-
(NT)1133(c)(EC0)	Z-Di	=(NT)1101(c)(EC0):33V	2c	Ntn	-
(NT)1203(c)(EC0)	Z-Di	3,9V,15W(Tc=45o),10%(c=5%)	32a$	Ntn	BZX98/..,BZY93/..
(NT)1204(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):4,7V	32a$	Ntn	-
(NT)1205(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):5,6V	32a$	Ntn	-
(NT)1206(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):6,8V	32a$	Ntn	-
(NT)1207(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):7,5V	32a$	Ntn	-
(NT)1208(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):8,2V	32a$	Ntn	-
(NT)1209(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):9,1V	32a$	Ntn	-
(NT)1210(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):10V	32a$	Ntn	-
(NT)1211(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):11V	32a$	Ntn	-
(NT)1212(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):12V	32a$	Ntn	-
(NT)1213(c)(EC0)	Z-Di	=(NT)1203(c)(EC0):13V	32a$	Ntn	-
(NT)1215(c)(EC0)	Z-Di	→(NT)4124(c)(EC0)	32a$	Ntn	-
(NT)1216(c)(EC0)	Z-Di	→(NT)4125(c)(EC0)	32a$	Ntn	-
(NT)1218(c)(EC0)	Z-Di	→(NT)4126(c)(EC0)	32a$	Ntn	-
(NT)1220(c)(EC0)	Z-Di	→(NT)4127(c)(EC0)	32a$	Ntn	-
(NT)1222(c)(EC0)	Z-Di	→(NT)4128(c)(EC0)	32a$	Ntn	-
(NT)1224(c)(EC0)	Z-Di	→(NT)4129(c)(EC0)	32a$	Ntn	-
(NT)1227(c)(EC0)	Z-Di	→(NT)4130(c)(EC0)	32a$	Ntn	-
(NT)1230(c)(EC0)	Z-Di	→(NT)4131(c)(EC0)	32a$	Ntn	-
(NT)1233(c)(EC0)	Z-Di	→(NT)4132(c)(EC0)	32a$	Ntn	-
(NT)1236(c)(EC0)	Z-Di	→(NT)4133(c)(EC0)	32a$	Ntn	-
(NT)1239(c)(EC0)	Z-Di	→(NT)4134(c)(EC0)	32a$	Ntn	-
(NT)1243(c)(EC0)	Z-Di	→(NT)4135(c)(EC0)	32a$	Ntn	-
(NT)1247(c)(EC0)	Z-Di	→(NT)4136(c)(EC0)	32a$	Ntn	-

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(NT)1301(c)(EC0)	Z-Di	2,7V,1W,10%(c=5%)	31a	Ntn	BZW22/..,BZX61/..,ZPY..,1N4728..4743+
(NT)1302(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):3,3V	31a	Ntn	-
(NT)1303(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):3,9V	31a	Ntn	-
(NT)1304(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):4,7V	31a	Ntn	-
(NT)1305(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):5,6V	31a	Ntn	-
(NT)1306(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):6,8V	31a	Ntn	-
(NT)1307(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):7,5V	31a	Ntn	-
(NT)1308(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):8,2V	31a	Ntn	-
(NT)1309(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):9,1V	31a	Ntn	-
(NT)1310(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):10V	31a	Ntn	-
(NT)1311(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):11V	31a	Ntn	-
(NT)1312(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):12V	31a	Ntn	-
(NT)1313(c)(EC0)	Z-Di	=(NT)1301(c)(EC0):13V	31a	Ntn	-
(NT)1315(c)(EC0)	Z-Di	→(NT)5324(c)(EC0)	31a	Ntn	-
(NT)1316(c)(EC0)	Z-Di	→(NT)5325(c)(EC0)	31a	Ntn	-
(NT)1318(c)(EC0)	Z-Di	→(NT)5326(c)(EC0)	31a	Ntn	-
(NT)1320(c)(EC0)	Z-Di	→(NT)5327(c)(EC0)	31a	Ntn	-
(NT)1322(c)(EC0)	Z-Di	→(NT)5328(c)(EC0)	31a	Ntn	-
(NT)1324(c)(EC0)	Z-Di	→(NT)5329(c)(EC0)	31a	Ntn	-
(NT)1327(c)(EC0)	Z-Di	→(NT)5330(c)(EC0)	31a	Ntn	-
(NT)1330(c)(EC0)	Z-Di	→(NT)5331(c)(EC0)	31a	Ntn	-
(NT)1333(c)(EC0)	Z-Di	→(NT)5332(c)(EC0)	31a	Ntn	-
(NT)1336(c)(EC0)	Z-Di	→(NT)5333(c)(EC0)	31a	Ntn	-
(NT)1339(c)(EC0)	Z-Di	→(NT)5334(c)(EC0)	31a	Ntn	-
(NT)1343(c)(EC0)	Z-Di	→(NT)5335(c)(EC0)	31a	Ntn	-
(NT)1347(c)(EC0)	Z-Di	→(NT)5336(c)(EC0)	31a	Ntn	-
(NT)1405(EC0)	Z-Di	→(NT)1305(EC0)	-	Ntn	-
(NT)1406(EC0)	Z-Di	→(NT)1306(EC0)	-	Ntn	-
(NT)1408(EC0)	Z-Di	→(NT)1308(EC0)	-	Ntn	-
(NT)1410(EC0)	Z-Di	→(NT)1310(EC0)	-	Ntn	-
(NT)1412(EC0)	Z-Di	→(NT)1312(EC0)	-	Ntn	-
(NT)1415(EC0)	Z-Di	→(NT)5324(EC0)	-	Ntn	-
(NT)1418(EC0)	Z-Di	→(NT)5326(EC0)	-	Ntn	-
(NT)1422(EC0)	Z-Di	→(NT)5328(EC0)	-	Ntn	-
(NT)1427(EC0)	Z-Di	→(NT)5330(EC0)	-	Ntn	-
(NT)1433(EC0)	Z-Di	→(NT)5332(EC0)	-	Ntn	-
(NT)1439(EC0)	Z-Di	→(NT)5334(EC0)	-	Ntn	-
(NT)1447(EC0)	Z-Di	→(NT)5336(EC0)	-	Ntn	-
(NT)2301(EC0)	Si-Di	Uni,S,220V,0,05A,1,5?s	31a	Ntn	BA147/230,BAY21,BAY46,1N5196,+
(NT)2302(EC0)	Si-Di	=(NT)2301(EC0):ohne DrДhte/wo.wires	-	Ntn	BA147/230,BAY21,BAY46,1N5196,+
(NT)2303(EC0)	Si-Di	=(NT)2301(EC0):100V,0,5A	31a	Ntn	BA157..159,BA193..194,BY402..405,+
(NT)2304(EC0)	Si-Di	=(NT)2301(EC0):50V	31a	Ntn	BA147/50,BAY18..21,1N5194..96,+
(NT)2401(EC0)	Si-Di	Uni,S,25V,0,1A,<2,5?s	31a	Ntn	BA147/50,BAY18..21,1N5194..96,+
(NT)2403(EC0)	Si-Di	=(NT)2401(EC0):55V	31a	Ntn	BA147/50,BAY18..21,1N5194..96,+
(NT)2405(EC0)	Si-Di	=(NT)2401(EC0):80V	31a	Ntn	BA147/100,BAY19..21,1N5195..96,+
(NT)2410(EC0)	Si-Di	=(NT)2401(EC0):150V	31a	Ntn	BA147/150,BAY20..21,1N5195..96,+
(NT)2415(EC0)	Si-Di	=(NT)2401(EC0):200V	31a	Ntn	BA147/230,BAY21,1N5195..96,+
(NT)2420(EC0)	Si-Di	=(NT)2401(EC0):250V	31a	Ntn	BA147/300,BAY21,BAY46,1N5196,+
(NT)2502(EC0)	Si-Di	GI,S,200V,0,6A,5?s	31a	Ntn	BY126..127,BY133..134,1N4003..07,+
(NT)2504(EC0)	Si-Di	=(NT)2502(EC0):400V	31a	Ntn	BY126..127,BY133..134,1N4004..07,+
(NT)2506(EC0)	Si-Di	=(NT)2502(EC0):600V	31a	Ntn	BY126..127,BY133..134,1N4005..07,+
(NT)2602(EC0)	Si-Di	GI/S-L,200V,3A(Tc=100o)	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2602..06R(EC0)	Si-Di	=(NT)2602(EC0):	32a$	Ntn	BYX38/..,BYX39/..
(NT)2604(EC0)	Si-Di	=(NT)2602(EC0):400V	32b&	Ntn	BYX38/600R,BYX39/600R
(NT)2606(EC0)	Si-Di	=(NT)2602(EC0):600V	32b&	Ntn	BYX38/600R,BYX39/600R
(NT)2611(EC0)	Si-Di	GI/S-L,100V,6A(Tc=100o)	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2611..14R(EC0)	Si-Di	=(NT)2611(EC0):	32a$	Ntn	BYX38/..,BYX39/..
(NT)2612(EC0)	Si-Di	=(NT)2611(EC0):200V	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2614(EC0)	Si-Di	=(NT)2611(EC0):400V	32b&	Ntn	BYX38/600R,BYX39/600R
(NT)2702(EC0)	Si-Di	GI/S-L,20V,3A(Tc=100o)	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2702..10R(EC0)	Si-Di	=(NT)2702(EC0):	32a$	Ntn	BYX38/..,BYX39/..
(NT)2705(EC0)	Si-Di	=(NT)2702(EC0):50V	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2710(EC0)	Si-Di	=(NT)2702(EC0):100V	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)2912(EC0)	Si-Di	GI,S,500V,0,1A,<2,5?s	-	Ntn	BA158..159,BAY89..91,BY203/12,+

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(NT)2913(EC0)	Si-Di	=(NT)2912(EC0):750V	-	Ntn	BA159,BAY90..91,BY203/12,+
(NT)2914(EC0)	Si-Di	=(NT)2912(EC0):1000V	-	Ntn	BA159,BAY90..91,BY203/12,+
(NT)2915(EC0)	Si-Di	=(NT)2912(EC0):1250V	-	Ntn	BAY91,BY203/12,RGP01-12,SHG1,5
(NT)2916(EC0)	Si-Di	=(NT)2912(EC0):1500V	-	Ntn	BAY91,BY203/16,RGP01-16,SHG1,5
(NT)2917(EC0)	Si-Di	=(NT)2912(EC0):1750V	-	Ntn	BAY91,BY203/20,BY584,SHG2
(NT)2918(EC0)	Si-Di	=(NT)2912(EC0):2000V	-	Ntn	BAY91,BY203/20,SHG2
(NT)3004(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3024(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3034(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3035(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3104(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3124(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3235(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3377(EC0)	Si-St	1V(1,5A),1,5W	31a	Ntn	ZY1
(NT)3390(EC0)	Si-St	1V(0,1A),0,4W	31a	Ntn	BA315,BZX62,BZX97/C0V8
(NT)3391(EC0)	Si-St	=(NT)3390(EC0):0,25W	2c	Ntn	BA315,BZX62,BZX97/C0V8
(NT)3392(EC0)	Si-St	L,1,5V(2A),15W	32	Ntn	-
(NT)3393(EC0)	Si-St	1,2V(0,5A),1W	31a	Ntn	-
(NT)3396(EC0)	Si-St	sym,n1V(n0,1A),0,25W	2c	Ntn	-
(NT)3397(EC0)	Si-St	sym,n0,56..0,68V(n1mA),2,5W	?31	Ntn	-
(NT)3398(EC0)	Si-St	sym,n0,6..0,72V(n1mA),2,5W	?31	Ntn	-
(NT)3535(EC0)	Ref-Di	Referenz-Modul	-	Ntn	-
(NT)3701(G)(EC0)	Ref-Di	5,9..6,5V	31a	Ntn	BZV13,BZV30,BZX93,1N828,1N4583,+
(NT)3702(G)(EC0)	Ref-Di	5,9,,6,5V	31a	Ntn	BZV19,BZV29,BZX92,1N825,1N4582,+
(NT)3703(G)(EC0)	Ref-Di	5,9..6,5V	31a	Ntn	BZV11,BZV28,BZX91,1N823,1N4581,+
(NT)3704(G)(EC0)	Ref-Di	5,9..6,5V	31a	Ntn	BZV10,BZV27,BZX90,1N821,1N4580,+
(NT)3705(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	-
(NT)3706(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	1N4894,1N4895
(NT)3707(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	1N4893,1N4894
(NT)3710(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	-
(NT)3711(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	-
(NT)3712(EC0)	Ref-Di	6,1..6,5V	31a	Ntn	BZV14,BZV31,BZX94,1N829,1N4584,+
(NT)3713(EC0)	Ref-Di	6,6V	31a	Ntn	-
(NT)3714(EC0)	Ref-Di	6,6V	31a	Ntn	-
(NT)3722(EC0)	Ref-Di	8..8,8V	31a	Ntn	BZX51,1N4780
(NT)3723(EC0)	Ref-Di	8..8,8V	31a	Ntn	BZX52,1N4781
(NT)3724(EC0)	Ref-Di	8..8,8V	31a	Ntn	BZX53,1N4782
(NT)3725(EC0)	Ref-Di	8..8,8V	31a	Ntn	BZX54,1N4783
(NT)3731(EC0)	Ref-Di	8..8,8V	31a	Ntn	-
(NT)3732(EC0)	Ref-Di	8..8,8V	31a	Ntn	-
(NT)3733(EC0)	Ref-Di	8..8,8V	31a	Ntn	-
(NT)3801..04(EC0)	Z-Di	Module	-	Ntn	-
(NT)4120(c)(EC0)	Z-Di	10V,15W,10%(c=5%)	32a$	Ntn	BZX98/..,BZY93/..
(NT)4121(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):11V	32a$	Ntn	-
(NT)4122(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):12V	32a$	Ntn	-
(NT)4123(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):13V	32a$	Ntn	-
(NT)4124(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):15V	32a$	Ntn	-
(NT)4125(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):16V	32a$	Ntn	-
(NT)4126(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):18V	32a$	Ntn	-
(NT)4127(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):20V	32a$	Ntn	-
(NT)4128(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):22V	32a$	Ntn	-
(NT)4129(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):24V	32a$	Ntn	-
(NT)4130(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):27V	32a$	Ntn	-
(NT)4131(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):30V	32a$	Ntn	-
(NT)4132(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):33V	32a$	Ntn	-
(NT)4133(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):36V	32a$	Ntn	-
(NT)4134(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):39V	32a$	Ntn	-
(NT)4135(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):43V	32a$	Ntn	-
(NT)4136(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):47V	32a$	Ntn	-
(NT)4137(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):51V	32a$	Ntn	-
(NT)4138(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):56V	32a$	Ntn	-
(NT)4139(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):62V	32a$	Ntn	-
(NT)4140(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):68V	32a$	Ntn	-
(NT)4141(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):75V	32a$	Ntn	-

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(NT)4142(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):82V	32a$	Ntn	-
(NT)4143(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):91V	32a$	Ntn	-
(NT)4144(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):100V	32a$	Ntn	-
(NT)4145(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):110V	32a$	Ntn	-
(NT)4146(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):120V	32a$	Ntn	-
(NT)4147(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):135V	32a$	Ntn	-
(NT)4148(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):150V	32a$	Ntn	-
(NT)4149(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):165V	32a$	Ntn	-
(NT)4150(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):180V	32a$	Ntn	-
(NT)4151(c)(EC0)	Z-Di	=(NT)4120(c)(EC0):200V	32a$	Ntn	-
(NT)4220..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):	32b&	Ntn	BZY93/..R
(NT)4320..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):20W	32a$	Ntn	BZY93/..
(NT)4420..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):20W	32b&	Ntn	BZY93/..R
(NT)4520..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):30W	32a$	Ntn	BZY91/.., 1N3309R..3350R
(NT)4620..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):30W	32b	Ntn	BZY91/..R, 1N3309..3350
(NT)4720..51(EC0)	Z-Di	=(NT)4120..4151(c)(EC0):bidirektional	32	Ntn	-
(NT)4820..51(EC0)	Z-Di	=(NT)4320..4151(c)(EC0):bidirektional	32	Ntn	-
(NT)4920..51(EC0)	Z-Di	=(NT)4520..4151(c)(EC0):bidirektional	32	Ntn	-
(NT)5120..51(EC0)	Z-Di	=(NT)5320..5351(c)(EC0)	31a	Ntn	→(NT)5320..5331
(NT)5220..51(EC0)	Z-Di	=(NT)5320..5351(c)(EC0):bidirektional	31	Ntn	-
(NT)5320(c)(EC0)	Z-Di	10V,1W,10%(c=5%)	31a	Ntn	BZW22/..,BZX61/..,ZPY..,1N4740..4764+
(NT)5321(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):11V	31a	Ntn	-
(NT)5322(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):12V	31a	Ntn	-
(NT)5323(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):13V	31a	Ntn	-
(NT)5324(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):15V	31a	Ntn	-
(NT)5325(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):16V	31a	Ntn	-
(NT)5326(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):18V	31a	Ntn	-
(NT)5327(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):20V	31a	Ntn	-
(NT)5328(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):22V	31a	Ntn	-
(NT)5329(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):24V	31a	Ntn	-
(NT)5330(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):27V	31a	Ntn	-
(NT)5331(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):30V	31a	Ntn	-
(NT)5332(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):33V	31a	Ntn	-
(NT)5333(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):36V	31a	Ntn	-
(NT)5334(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):39V	31a	Ntn	-
(NT)5335(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):43V	31a	Ntn	-
(NT)5336(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):47V	31a	Ntn	-
(NT)5337(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):51V	31a	Ntn	-
(NT)5338(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):56V	31a	Ntn	-
(NT)5339(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):62V	31a	Ntn	-
(NT)5340(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):68V	31a	Ntn	-
(NT)5341(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):75V	31a	Ntn	-
(NT)5342(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):82V	31a	Ntn	-
(NT)5343(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):91V	31a	Ntn	-
(NT)5344(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):100V	31a	Ntn	-
(NT)5345(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):110V	31a	Ntn	-
(NT)5346(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):120V	31a	Ntn	-
(NT)5347(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):135V	31a	Ntn	-
(NT)5348(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):150V	31a	Ntn	-
(NT)5349(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):165V	31a	Ntn	-
(NT)5350(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):180V	31a	Ntn	-
(NT)5351(c)(EC0)	Z-Di	=(NT)5320(c)(EC0):200V	31a	Ntn	-
(NT)5420..51(EC0)	Z-Di	=(NT)5320..5351(c)(EC0):bidirektional	31a	Ntn	-
(NT)5501(EC0)	Si-St	=NT55/C0V7	31a	Ntn	→NT55/C0V7
(NT)5502(EC0)	Si-St	=NT55/C1V4	31a	Ntn	→NT55/C1V4
(NT)5503(EC0)	Si-St	=NT55/2V1	31a	Ntn	→NT55/C2V1
(NT)5506(G)(EC0)	Z-Di	2,7V,0,5W,5%,(=NT55/C..)	31a	Ntn	BZX55/..,BZX83/..,ZPD..,1N5223..81,+
(NT)5507(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):3V	31a	Ntn	-
(NT)5508(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):3,3V	31a	Ntn	-
(NT)5509(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):3,6V	31a	Ntn	-
(NT)5510(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):3,9V	31a	Ntn	-
(NT)5511(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):4,3V	31a	Ntn	-
(NT)5512(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):4,7V	31a	Ntn	-
(NT)5513(G)(EC0)	Z-Di	=(NT)5506(G)(EC0):5,1V	31a	Ntn	-

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(NT)5514(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):5,6V	31a	Ntn	-
(NT)5515(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):6,2V	31a	Ntn	-
(NT)5516(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):6,8V	31a	Ntn	-
(NT)5517(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):7,5V	31a	Ntn	-
(NT)5518(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):8,2V	31a	Ntn	-
(NT)5519(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):9,1V	31a	Ntn	-
(NT)5520(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):10V	31a	Ntn	-
(NT)5521(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):11V	31a	Ntn	-
(NT)5522(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):12V	31a	Ntn	-
(NT)5523(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):13V	31a	Ntn	-
(NT)5524(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):15V	31a	Ntn	-
(NT)5525(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):16V	31a	Ntn	-
(NT)5526(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):18V	31a	Ntn	-
(NT)5527(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):20V	31a	Ntn	-
(NT)5528(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):22V	31a	Ntn	-
(NT)5529(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):24V	31a	Ntn	-
(NT)5530(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):27V	31a	Ntn	-
(NT)5531(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):30V	31a	Ntn	-
(NT)5532(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):33V	31a	Ntn	-
(NT)5533(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):36V	31a	Ntn	-
(NT)5534(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):39V	31a	Ntn	-
(NT)5535(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):43V	31a	Ntn	-
(NT)5536(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):47V	31a	Ntn	-
(NT)5537(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):51V	31a	Ntn	-
(NT)5538(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):56V	31a	Ntn	-
(NT)5539(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):62V	31a	Ntn	-
(NT)5540(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):68V	31a	Ntn	-
(NT)5541(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):75V	31a	Ntn	-
(NT)5542(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):82V	31a	Ntn	-
(NT)5543(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):91V	31a	Ntn	-
(NT)5544(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):100V	31a	Ntn	-
(NT)5545(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):110V	31a	Ntn	-
(NT)5546(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):120V	31a	Ntn	-
(NT)5547(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):130V	31a	Ntn	-
(NT)5548(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):150V	31a	Ntn	-
(NT)5549(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):160V	31a	Ntn	-
(NT)5550(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):180V	31a	Ntn	-
(NT)5551(G)(EC0).	Z-Di	=(NT)5506(G)(EC0):200V	31a	Ntn	-
(NT)7701(EC0)	Si-St	=NT77/C0V7	31a	Ntn	→NT77/0V7
(NT)7702(EC0)	Si-St	=NT77/1V4	31a	Ntn	→NT77/1V4
(NT)7706(EC0)	Z-Di	2,7V,1,5W,5%,(=NT77/..)	31a	Ntn	BZV47/..,BZY97/..,ZY..,1N5913..5956
(NT)7707(EC0)	Z-Di	=(NT)7706(EC0):3V	31a	Ntn	-
(NT)7708(EC0)	Z-Di	=(NT)7706(EC0):3,3V	31a	Ntn	-
(NT)7709(EC0)	Z-Di	=(NT)7706(EC0):3,6V	31a	Ntn	-
(NT)7710(EC0)	Z-Di	=(NT)7706(EC0):3,9V	31a	Ntn	-
(NT)7711(EC0)	Z-Di	=(NT)7706(EC0):4,3V	31a	Ntn	-
(NT)7712(EC0)	Z-Di	=(NT)7706(EC0):4,7V	31a	Ntn	-
(NT)7713(EC0)	Z-Di	=(NT)7706(EC0):5,1V	31a	Ntn	-
(NT)7714(EC0)	Z-Di	=(NT)7706(EC0):5,6V	31a	Ntn	-
(NT)7715(EC0)	Z-Di	=(NT)7706(EC0):6,2V	31a	Ntn	-
(NT)7716(EC0)	Z-Di	=(NT)7706(EC0):6,8V	31a	Ntn	-
(NT)7717(EC0)	Z-Di	=(NT)7706(EC0):7,5V	31a	Ntn	-
(NT)7718(EC0)	Z-Di	=(NT)7706(EC0):8,2V	31a	Ntn	-
(NT)7719(EC0)	Z-Di	=(NT)7706(EC0):9,1V	31a	Ntn	-
(NT)7720(EC0)	Z-Di	=(NT)7706(EC0):10V	31a	Ntn	-
(NT)7721(EC0)	Z-Di	=(NT)7706(EC0):11V	31a	Ntn	-
(NT)7722(EC0)	Z-Di	=(NT)7706(EC0):12V	31a	Ntn	-
(NT)7723(EC0)	Z-Di	=(NT)7706(EC0):13V	31a	Ntn	-
(NT)7724(EC0)	Z-Di	=(NT)7706(EC0):15V	31a	Ntn	-
(NT)7725(EC0)	Z-Di	=(NT)7706(EC0):16V	31a	Ntn	-
(NT)7726(EC0)	Z-Di	=(NT)7706(EC0):18V	31a	Ntn	-
(NT)7727(EC0)	Z-Di	=(NT)7706(EC0):20V	31a	Ntn	-
(NT)7728(EC0)	Z-Di	=(NT)7706(EC0):22V	31a	Ntn	-
(NT)7729(EC0)	Z-Di	=(NT)7706(EC0):24V	31a	Ntn	-

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(NT)7730(EC0)	Z-Di	=(NT)7706(EC0):27V	31a	Ntn	-
(NT)7731(EC0)	Z-Di	=(NT)7706(EC0):30V	31a	Ntn	-
(NT)7732(EC0)	Z-Di	=(NT)7706(EC0):33V	31a	Ntn	-
(NT)7733(EC0)	Z-Di	=(NT)7706(EC0):36V	31a	Ntn	-
(NT)7734(EC0)	Z-Di	=(NT)7706(EC0):39V	31a	Ntn	-
(NT)7735(EC0)	Z-Di	=(NT)7706(EC0):43V	31a	Ntn	-
(NT)7736(EC0)	Z-Di	=(NT)7706(EC0):47V	31a	Ntn	-
(NT)7737(EC0)	Z-Di	=(NT)7706(EC0):51V	31a	Ntn	-
(NT)7738(EC0)	Z-Di	=(NT)7706(EC0):56V	31a	Ntn	-
(NT)7739(EC0)	Z-Di	=(NT)7706(EC0):62V	31a	Ntn	-
(NT)7740(EC0)	Z-Di	=(NT)7706(EC0):68V	31a	Ntn	-
(NT)7741(EC0)	Z-Di	=(NT)7706(EC0):75V	31a	Ntn	-
(NT)7742(EC0)	Z-Di	=(NT)7706(EC0):82V	31a	Ntn	-
(NT)7743(EC0)	Z-Di	=(NT)7706(EC0):91V	31a	Ntn	-
(NT)7744(EC0)	Z-Di	=(NT)7706(EC0):100V	31a	Ntn	-
(NT)7745(EC0)	Z-Di	=(NT)7706(EC0):110V	31a	Ntn	-
(NT)7746(EC0)	Z-Di	=(NT)7706(EC0):120V	31a	Ntn	-
(NT)7747(EC0)	Z-Di	=(NT)7706(EC0):130V	31a	Ntn	-
(NT)7748(EC0)	Z-Di	=(NT)7706(EC0):150V	31a	Ntn	-
(NT)7749(EC0)	Z-Di	=(NT)7706(EC0):160V	31a	Ntn	-
(NT)7750(EC0)	Z-Di	=(NT)7706(EC0):180V	31a	Ntn	-
(NT)7751(EC0)	Z-Di	=(NT)7706(EC0):200V	31a	Ntn	-
(NT)9015(EC0)	Si-Di	log. Sperrkennlinie/reverse charact.	31a	Ntn	-
(NT)9400..23(EC0)	Si-Di,Z-Di	nicht dokumentiert/no data available	-	old	-
(NT)9425..99(EC0)	Si-Di,Z-Di	nicht dokumentiert/no data available	-	old	-
(NT)9605(EC0)	Z-Di	5,8..6,6V,0,125W	2c	Ntn	-
(NT)9606(EC0)	Z-Di	=(NT)9605:6,4..7,2V	2c	Ntn	-
(NT)9607(EC0)	Z-Di	=(NT)9605:7,1..7,9V	2c	Ntn	-
(NT)9624(EC0)	Si-Di	kV-Gl,5kV,0,1A,<2?s	-	Ntn	1N5182
(NT)9648(EC0)	Si-Di	Gl/S-L,200V,2A	32b&	Ntn	BYX38/300R,BYX39/600R
(NT)9649(EC0)	Si-Di	kV-Gl,1,4kV,0,1A,<5?s	-	Ntn	1N1732
(NT)9650(EC0)	Si-Di	=(NT)9649(EC0):2,8kV	-	Ntn	1N1733
(NT)9651(EC0)	Si-Di	=(NT)9649(EC0):4,2kV	-	Ntn	1N1734
(NT)9652(EC0)	Si-Di	=(NT)9649(EC0):5,6kV	-	Ntn	BYX90
(NT)9689(EC0)	Si-Di	Gl/S-L,100V,6A,<300ns	32a$	Ntn	1N3880..3883
(NT)9690(EC0)	Si-Di	=(NT)9689(EC0):	32b&	Ntn	1N3880R..3883R
(NT)9700..78(EC0)	Si-Di,Z-Di	nicht dokumentiert/no data available	-	old	-
(NT)9779(EC0)	Si-Di	=(NT)9015(EC0):0,25W	2c	Ntn	-
(NT)9780..99(EC0)	Si-Di,Z-Di	nicht dokumentiert/no data available	-	old	-
(NT)9832c(EC0)	Si-Di	Kontaktschutz/contact protect	31a	Ntn	-
(NT)9970(EC0)	Z-Di	3V,0,25W	2c	Ntn	BZX55/..,BZX79/..,ZPD..,1N4683..90,+
(NT)9971(EC0)	Z-Di	=(NT)9970:3,6V	2c	Ntn	-
(NT)9972(EC0)	Z-Di	=(NT)9970:4,3V	2c	Ntn	-
(NT)9973(EC0)	Z-Di	=(NT)9970:5,1V	2c	Ntn	-
(NT)9974(EC0)	Z-Di	=(NT)9970:6,2V	2c	Ntn	-
(NT)9980(EC0)	Z-Di	3V,1W	31a	Ntn	BZW22/..,BZX61/..,ZPY..,1N5913..20,+
(NT)9981(EC0)	Z-Di	=(NT)9980:3,6V	31a	Ntn	-
(NT)9982(EC0)	Z-Di	=(NT)9980:4,3V	31a	Ntn	-
(NT)9983(EC0)	Z-Di	=(NT)9980:5,1V	31a	Ntn	-
(NT)9984(EC0)	Z-Di	=(NT)9980:6,2V	31a	Ntn	-
(NT)9992(EC0)	Z-Di	4,3V,15W	32a$	Ntn	BZX98/..,BZY93/..
(NT)9993(EC0)	Z-Di	=(NT)9992:5,1V	32a$	Ntn	-
(NT)9994(EC0)	Z-Di	=(NT)9992:6,2V	32a$	Ntn	-
(SI-)3050C	Hybrid-Z-IC	VC,+5V,1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3050C,CA	Hybrid-Z-IC	lo-drop,+5V±4%(CA:±2%),1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3052P	Hybrid-Z-IC	+5V,2A,50W	18a	Sak	-
(SI-)3052V	Hybrid-Z-IC	lo-drop,+5V,2A,50W	18f	Sak	-
(SI-)3082P	Hybrid-Z-IC	+8V,2A,50W	18a	Sak	-
(SI-)3090C	Hybrid-Z-IC	VC,+9V,1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3090C,CA	Hybrid-Z-IC	lo-drop,+9V±4%(CA:±2%),1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3120C,CA	Hybrid-Z-IC	lo-drop,±12V±4%(CA:±2%),1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3120C,CS	Hybrid-Z-IC	VC,+12V±5%(CS=±2%),1,5A,18W,Iso	86/5Pin	Sak	-
(SI-)3122P	Hybrid-Z-IC	+12V,2A,50W	18a	Sak	-
(SI-)3122V	Hybrid-Z-IC	lo-drop,+12V,2A,50W	18f	Sak	-

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(SI-)3150C	Hybrid-Z-IC	VC, +15V, 1,5A, 18W, Iso	86/5Pin	Sak	-
(SI-)3150C,CA	Hybrid-Z-IC	lo-drop, +15V ±4% (CA: ±2%), 1,5A, 18W, Iso	86/5Pin	Sak	-
(SI-)3152P	Hybrid-Z-IC	+15V, 2A, 50W	18a	Sak	-
(SI-)3152V	Hybrid-Z-IC	lo-drop, +15V, 2A, 50W	18f	Sak	-
(SI-)3240C	Hybrid-Z-IC	VC, +24V, 1,5A, 18W, Iso	86/5Pin	Sak	-
(SI-)3240C,CA	Hybrid-Z-IC	lo-drop, +24V ±4% (CA: ±2%), 1,5A, 18W, Iso	86/5Pin	Sak	-
(SI-)3242P	Hybrid-Z-IC	+24V, 2A, 50W	18a	Sak	-
(SSi)B0510...0580	Si-Di	→SSiB0510..0580	27c	Sie	-
(SSi)B0810...0880	Si-Di	→SSiB0810..0880	31a	Sie	-
(SSi)C1710	Si-Di	→SSiC1710	27c	Sie	-
(SSi)C1720	Si-Di	→SSiC1720	27c	Sie	-
(SSi)C1740	Si-Di	→SSiC1740	27c	Sie	-
(SSi)C1760	Si-Di	→SSiC1760	27c	Sie	-
(SSi)C1780	Si-Di	→SSiC1780	27c	Sie	-
(SSi)C2620	Si-Di	→SSiC2620	31a	Sie	-
(SSi)C2630	Si-Di	→SSiC2630	31a	Sie	-
(SSi)C4610	Si-Di	→SSiC4610	-	Sie	-
(SSi)C4620	Si-Di	→SSiC4620	-	Sie	-
(T1,T3)	Z-Di	(=1N5221B..5272B)	-		-
(T3)	Z-Di	(=1N5920..5941)	-		-
(T3)	Z-Di	=BZW06-6V8..200:SMD	-		-
.4M.64FR10	Si-St	Stabi, 0,58..0,7V/1mA	31a	Mot	BZX62, BZX83/C0V8, BZX97/0V8
.4M1.36FR2	Si-St	Stabi, 1,33..1,39V/1mA	31a	Mot	BZ102/1V4, BZV86/1V4, BZX75/C1V4)
.4M1.36FR5	Si-St	Stabi, 1,29..1,43V/1mA	31a	Mot	BZ102/1V4, BZV86/1V4, BZX75/C1V4)
.4M2.04FR2	Si-St	Stabi, 2,00..2,08V/1mA	31a	Mot	BZ102/2V1, BZV86/2V0, BZX75/C2V1)
.4M2.04FR5	Si-St	Stabi, 1,94..2,14V/1mA	31a	Mot	BZ102/2V1, BZV86/2V0, BZX75/C2V1)
.A1	Si-Di	=1SS382 (Typ-Code/Stempel/marking)	44(2mm)	Tos	→1SS382
.A4	Si-Di	=1SS383 (Typ-Code/Stempel/marking)	44(2mm)	Tos	→1SS383
.A5	Si-Di	=1SS384 (Typ-Code/Stempel/marking)	44(2mm)	Tos	→1SS384
+P2	Si-N	=BFR92A (Typ-Code/Stempel/marking)	35	Aeg	→BFR92A
+P5	Si-N	=BFR92AR (Typ-Code/Stempel/marking)	35	Aeg	→BFR92AR
+R2	Si-N	=BFR93A (Typ-Code/Stempel/marking)	35	Aeg	→BFR93A
+R5	Si-N	=BFR93AR (Typ-Code/Stempel/marking)	35	Aeg	→BFR93AR
µA101(A)DMQB	Op-IC	Series 101, ±22V, -55..+125°: Hi-rel	14-DIP	Fairchild	-
µA101(A)FMQB	Op-IC	Series 101, ±22V, -55..+125°: Hi-rel	10-FLP	Fch	-
µA101(A)HM(QB)	Op-IC	Series 101, ±22V, -55..+125°	81	Fch	-
µA105HM,HMQB	VR-IC	+4,5..40V, 12mA, -55..+125°	81	Fch	LM105H
µA108(A)DMQB	Op-IC	Series 108, Lo-power, ±22V, -55..+125°: Hi-rel	14-DIP	Fairchild	-
µA108(A)FMQB	Op-IC	Series 108, Lo-power, ±22V, -55..+125°: Hi-rel	10-FLP	Fch	-
µA108(A)HM(QB)	Op-IC	Series 108, Lo-power, ±22V, -55..+125°	81	Fch	-
µA109HM(QB)	VR-IC	+5V, 1A, 2W, -55..+125°	2e	Fch	LM109H,LA
µA109KM(QB)	VR-IC	+5V, 1A, 2W, -55..+125°	23a	Fch	LM109K
µA110HM(QB)	Op-IC	Volt. follower, ±18V, -55..+125°	81	Fch	-
µA111DM(QB)	Comp-IC	Series 111, ±18V, 50mA, -55..+125°	14-DIP	Fairchild	-
µA111FM(QB)	Comp-IC	Series 111, ±18V, 50mA, -55..+125°	10-FLT	Fch	-
µA111HM(QB)	Comp-IC	Series 111, ±18V, 50mA, -55..+125°	81	Fch	-
µA111RM(QB)	Comp-IC	Series 111, ±18V, 50mA, -55..+125°	8-DIP	Fch	-
µA117HMQB	VR-IC	+1,2..37V, >0,5A, -55..+150°	2k	Fch	LM117H..
µA117KM,KMQB	VR-IC	+1,2..37V, >1,5A, -55..+150°	23k	Fch	LM117K..
µA124DM(QB)	Op-IC	Quad, Series 124, ±16V, -55..+125°	14-DIC	Fairchild	-
µA124FMQB	Op-IC	Quad, Series 124, ±16V, -55..+125°: Hi-rel	14-FLP	Fch	-
µA124LMQB	Op-IC	Quad, Series 124, ±16V, -55..+125°: Hi-rel	20-LCC	Fch	-
µA138KM,KMQB	VR-IC	+1,2..32V, >5A, -55..+150°	23k	Fch	LM138..
µA139DM(QB)	Comp-IC	Quad, Series 139, ±18V, -55..+125°	14-DIC	Fairchild	-
µA139FM(QB)	Comp-IC	Quad, Series 139, ±18V, -55..+125°	14-FLP	Fch	-
µA139LM(QB)	Comp-IC	Quad, Series 139, ±18V, -55..+125°	20-LCC	Fch	-
µA1458(C)HC	Op-IC	Dual, Series 158, ±18V, 0..+70°	81	Fch	-
µA1458(C)RC,TC	Op-IC	Dual, Series 158, ±18V, 0..+70°	8-DIC,DIP	Fch	-
µA1458SC	Op-IC	Dual, Series 158, ±18V, 0..+70°	8-MDIP	Fch	-
µA1488DC,PC	I/O-IC	4x Line Driver for RS232	14-DIC,DIP	Fairchild	DS1488..MC1488..HD1488..SN75188..XR-1488..
µA1488SC	I/O-IC	4x Line Driver for RS232	14-MDIP	NEC	-
µA1489(A)DC,PC	I/O-IC	4x Line Receiver for RS232	14-DIC,DIP	Fairchild	DS1489..HD1489..MC1489..SN75189..XR-1489..
µA1489SC	I/O-IC	4x Line Receiver for RS232	14-MDIP	NEC	-

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µA148DM(QB)	Op-IC	Quad, Series 124, ±22V, 1MHz, -55..+125°	14-DIP	Fairchild	-
µA150KM,KMQB	VR-IC	+1,2..33V, 3A, -55..+150°	23k	Fch	LM150K
µA1524ADM,ADMQB	Lin-IC	SMPS PWM Controller, 100mA, -55..+125°	16-DIC	Fch	→SG1524
µA1558HM(QB)	Op-IC	Dual, Series 158, ±22V, -55..+125°	81	Fch	-
µA1558RM(QB)	Op-IC	Dual, Series 158, ±22V, -55..+125°	8-DIC	Fch	-
µA201(A)HV	Op-IC	Series 101, ±22V, -25..+85°	81	Fch	-
µA201TC	Op-IC	Series 101, ±22V, -25..+85°	8-DIP	Fch	-
µA208(A)HV	Op-IC	Series 108, Lo-power, ±22V, -25..+85°	81	Fch	-
µA209KM	VR-IC	+5V, 1A, 2W, -25..+125°	23a	Fch	LM209K, µA109KM
µA2101(A)DMBQ	Op-IC	Dual, ±22V, -55..+125°	16-DIC	Fch	-
µA2108(A)DMBQ	Op-IC	Dual, Super Beta, ±22V, -55..+125°	16-DIC	Fch	-
µA2111DMBQ	Op-IC	Dual, ±18V, 50mA, -55..+125°	16-DIC	Fch	-
µA212..DV	CMOS-IC	Full duplex modem, 1200/300Bps, Int. DTMF Generator, -40..+85°	28-DIC	NEC	-
µA212..QC	CMOS-IC	Full duplex modem, 1200/300Bps, Int. DTMF Generator	28-MDIP	NEC	-
µA212ADC,APC	CMOS-IC	Telecom, full duplex modem, 1200/300Bps	28-DIC,DIP	Fch	-
µA212ATDC,ATPC	CMOS-IC	Full duplex modem, 1200/300Bps, Int. DTMF Generator	28-DIC,DIP	Fch	-
µA217KV	VR-IC	+1,2..37V, >1,5A, -40..+150°	23k	Fch	LM217..µA117K..
µA217UV	VR-IC	+1,2..37V, >1,5A, -40..+150°	17l	Fch	LM217..µA117U..
µA2240DC,PC	Lin-IC	Timer, Counter, progr., Ucc=4..15V	16-DIC,DIP	Fch	UA2240..
µA224DV,PV	Op-IC	Quad, Series 124, ±16V, -25..+85°	14-DIC,DIP	Fairchild	-
µA238KV	VR-IC	+1,2..32V, >5A, -40..+150°	23k	Fch	LM238..µA138K..
µA239DV,PV	Comp-IC	Quad, Series 139, ±18V, -25..+85°	14-DIC,DIP	Fairchild	-
µA239SV	Comp-IC	Quad, Series 139, ±18V, -25..+85°	14-MDIP	Fch	-
µA2460DC	Lin-IC	Hard Disk Servo Control	28-DIC	Fch	-
µA2460QC	Lin-IC	Hard Disk Servo Control	28-PLCC	NEC	-
µA2461DC	Lin-IC	Hard Disk Servo Control	28-DIC	Fch	-
µA2461QC	Lin-IC	Hard Disk Servo Control	28-PLCC	NEC	-
µA2470DC	Lin-IC	Hard Disk Position Demodulator	28-DIC	Fch	-
µA2480FC	Lin-IC	Hard Disk Position Demodulator	10-FLP	NEC	-
µA2480TC	Lin-IC	Hard Disk Servo Preamplifier	8-DIP	Fch	-
µA2482DC,RDC	Lin-IC	Hard Disk 2-Ch. Read/Write Preamp.	18-DIC	Fch	-
µA2482GC,RGC	LIn-IC	Hard Disk 2-Ch. Read/Write Preamp.	24-FLP	NEC	-
µA2484DC,RDC	Lin-IC	Hard Disk 4-Ch. Read/Write Preamp.	24-DIC	Fch	-
µA2484GC,RGC	Lin-IC	Hard Disk 4-Ch. Read/Write Preamp.	24-FLP	NEC	-
µA2485DC,RDC	Lin-IC	Hard Disk 5-Ch. Read/Write Preamp.	24-DIC	Fch	-
µA2485FC,RFC	Lin-IC	Hard Disk 5-Ch. Read/Write Preamp.	24-FLP	NEC	-
µA2485GC,RGC	Lin-IC	Hard Disk 5-Ch. Read/Write Preamp.	24-FLP	NEC	-
µA2486DC,RDC	Lin-IC	Hard Disk 6-Ch. Read/Write Preamp.	28-DIC	Fch	-
µA2486QC,RQC	Lin-IC	Hard Disk 6-Ch. Read/Write Preamp.	28-PLCC	NEC	-
µA2488GC,GDC	Lin-IC	Hard Disk 8-Ch. Read/Write Preamp.	32-FLP	Fch	-
µA2488QC,RQC	Lin-IC	Hard Disk 8-Ch. Read/Write Preamp.	44-PLCC	NEC	-
µA248DV,PV	Op-IC	Quad, Series 124, ±18V, 1MHz, -25..+85°	14-DIC,DIP	Fairchild	-
µA2490QC	Lin-IC	Hard Disk MFM/2,7 Data Sep., Decoder	44-PLCC	NEC	-
µA2490TC	Lin-IC	Hard Disk MFM/2,7 Data Sep., Decoder	28-DIP	Fch	-
µA24H80FC	Lin-IC	Hard Disk Servo Preamplifier	10-FLP	NEC	-
µA24H80RC,TC	Lin-IC	Hard Disk Servo Preamplifier	8-DIC,DIP	Fch	-
µA24H80SC	Lin-IC	Hard Disk Servo Preamplifier	8-MDIP	NEC	-
µA250KV	VR-IC	+1,2..33V, 3A, -25..+150°	23k	Fch	LM250K, µA150K..
µA2524ADV,APV	Lin-IC	PWM Power Control, Ucc=40V, Iout=100mA	16-DIC,DIP	Fch	SG2524N
µA2580DC	Lin-IC	Hard Disk Servo Preamplifier	8-DIC	Fch	-
µA2580FC	Lin-IC	Hard Disk Servo Preamplifier	10-FLP	NEC	-
µA2580SC	Lin-IC	Hard Disk Servo Preamplifier	8-MDIP	NEC	-
µA26LS31DC,PC	I/O-IC	4x Line Driver for RS422, 0..+70°	16-DIC,DIP	Fch	AM26LS31..DL2631..SN7517
µA26LS31DM(QB)	I/O-IC	4x Line Driver for RS422, -55..+125°	16-DIC	NEC	-
µA26LS31LM(QB)	I/O-IC	4x Line Driver for RS422, -55..+125°	20-LCC	NEC	-
µA26LS32DC,PC	I/O-IC	4x Line Receiver for RS422,423, 0..+70°	16-DIC,DIP	Fch	AM26L32..DL2632..SN75173
µA26LS32DM(QB)	I/O-IC	4x Line Receiver for RS422,423, -55..+125°	16-DIC	NEC	-
µA26LS32LM(QB)	I/O-IC	4x Line Receiver for RS422,423, -55..+125°	20-LCC	NEC	-
µA2901DV,PV	Comp-IC	Quad, Series 139, ±18V, -40..+85°	14-DIC,DIP	Fairchild	-
µA2902PV	Op-IC	Quad, Series 124, 26V, -40..+85°	14-DIP	Fairchild	-
µA301(A)HC	Op-IC	Series 101, ±18V, 0..+70°	81	Fch	-
µA301(A)SC	Op-IC	Series 101, ±18V, 0..+70°	8-MDIP	Fch	-
µA301(A)TC	Op-IC	Series 101, ±18V, 0..+70°	8-DIP	Fch	-
µA304SDM(QB)	Lin-IC	5x NPN-Trans, 20V, 0,05A, -55..+125°	14-DIC	Fairchild	CA3045, LM3045, TBA331

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µA3046PC	Lin-IC	5xNPN-Trans, 20V, 0,05A, 0..+70°	14-DIP	Fairchild	CA3046, LM3046, TBA331
µA3046SC	Lin-IC	5xNPN-Trans, 20V, 0,05A, 0..+70°	14-MDIP	Fch	-
µA3054	CMOS-IC	Telecom, µ-Law Combo Codec	16-DIC	STE	ETC5054, KT3030, KT8554, TP3054, 291
µA3057	CMOS-IC	Telecom, A-Law Combo Codec	16-DIC	Fch	ETC5057, KT3032, KT8557, TP3057, 291
µA305HC, AHC	VR-IC	+4,5..40V, 12mA, 0..+70°, A=45mA	81	Fch	LM305H
µA3065PC	Lin-IC	TV, Sound-IF, FM-IF	14-DIP	NEC	AN241, MC1358, LA1365
µA308(A)HC	Op-IC	Series 108, Lo-power, ±18V, 0..+70°	81	Fch	-
µA308(A)SC	Op-IC	Series 108, Lo-power, ±18V, 0..+70°	8-MDIP	Fch	-
µA308(A)TC	Op-IC	Series 108, Lo-power, ±18V, 0..+70°	8-DIP	Fch	-
µA3086DV, PV	Lin-IC	5xNPN-Trans, 20V, 0,05A, -40..+85°	14-DIC, DIP	Fairchild	CA3086, TBA331, LM3086
µA3086SC	Lin-IC	5xNPN-Trans, 20V, 0,05A, -40..+85°	14-MDIP	NEC	-
µA3089E	Lin-IC	TV-FM-IF	16-DIP	NEC	TDA1200(A)
µA309KC	VR-IC	=µA109HM: 0..+125°	23a	Fch	LM309K, ..7805.. (TO-3)
µA310C	Op-IC	=µA110HM: 0..+70°	81	Fch	-
µA311HC	Comp-IC	=µA111HM: 0..+70°	81	Fch	-
µA311SC	Comp-IC	=µA111HM: 0..+70°	8-MDIP	Fch	-
µA311TC	Comp-IC	=µA111HM: 0..+70°	8-DIP	Fch	-
µA317KC	VR-IC	=µA117KM: 0..+150°	23k	Fch	LM317..µA117K..µA217K..
µA317UC	VR-IC	=µA117KM: 0..+150°	171	Fch	LM317..µA117U..µA217U..
µA324DC, PC	Op-IC	Quad, Series 124, ±16V, 0..+70°	14-DIC, DIP	Fairchild	-
µA324SC	Op-IC	=µA124DM: 0..+70°	14-MDIP	Fch	-
µA3302DV, PV	Comp-IC	Quad, Series 139, ±14V, -40..+85°	14-DIC, DIP	Fairchild	-
µA3302SV	Comp-IC	Quad, Series 139, ±14V, -40..+85°	14-MDIP	Fch	-
µA3303DV, PV	Op-IC	Quad, Series 124, ±18V, -40..+85°	14-DIC, DIP	Fairchild	-
µA338KC	VR-IC	=µA138KM: 0..+150°	23k	Fch	LM338..µA138K..µA238K..
µA338UC	VR-IC	=µA138KM: 0..+150°	171	Fch	LM338..
µA339DC, PC	Comp-IC	Quad, Series 139, ±18V, 0..+70°	14-DIP	Fairchild	-
µA339SC	Comp-IC	=µA139DM: 0..+70°	14-MDIP	Fch	-
µA3486DC, PC	I/O-IC	4x Line Receiver for RS422/3	16-DIC, DIP	Fch	DS3486, MC3486, SN75175..
µA3487DC, PC	I/O-IC	4x Line Driver for RS422	16-DIC, DIP	Fch	DS3487, MC3487, SN75174..
µA348DC, PC	Op-IC	Quad, Series 124, ±18V, 0..+70°	14-DIC, DIP	Fairchild	-
µA3503DM	Op-IC	Quad, Series 124, ±18V, -55..+125°	14-DIC	Fairchild	-
µA350KC	VR-IC	=µA150KM: 0..+150°	23k	Fch	KA350H, LM150K, µA150K..жA
µA350UC	VR-IC	=µA150KM: 0..+150°	171	Fch	KA350, LM350T, KC
µA3524ADC, APC	Lin-IC	=SG3524..	16-DIC, DIP	Fch	SG3524
µA3680DV, PV	Lin-IC	Telecom, 4x Telephone Relay Driver	14-DIC, DIP	Fairchild	-
µA3680SV	Lin-IC	=µA3680DV, PV: SMD	14-MDIP	Fch	-
µA3748CT	Op-IC	=µA3748T: 0..+70°	81	NEC	-
µA3748T	Op-IC	GenP, Series 748, ±15V, -55..+125°	81	Fch	-
µA376TC	VR-IC	=µA105HM: 25mA, 0..+70°	8-DIP	Fch	LM376..
µA4136DC, PC	Op-IC	Quad, ±18V, 3MHz, 0..+70°	14-DIC, DIP	Fairchild	RC4136, RM4136, RV4136, XR-4
µA4136DM(QB)	Op-IC	Quad, ±18V, 3MHz, -55..+125°	14-DIC	Fairchild	RM4136, XR-4136M
µA4136SC	Op-IC	Quad, ±18V, 3MHz, 0..+70°	14-MDIP	Fch	RC4136D, RV4136D, µA4136SC
µA431ASC	Vref-IC	2,5..36V, 1..100mA, 0,75Ω	8-MDIP	NEC	-
µA431AWC, AWV	Vref-IC	2,5..36V, 1..100mA, 0,75Ω	7(KARef)	Fch	KA431..NJM431..TL431..
µA431LMQB	Vref-IC	2,5..36V, 1..100mA, 0,75Ω	20-LCC	NEC	-
µA431RMQB	Vref-IC	2,5..36V, 1..100mA, 0,75Ω	8-DIP	NEC	-
µA4558TC	Op-IC	Dual, Series 158, ±15V, 0..+70°	8-DIP	Fch	-
µA494DC, PC	Lin-IC	PWM Controller, 40V, 0,2A, 0..+70°	16-DIC, DIP	Fch	TL494..
µA494DMQB	Lin-IC	PWM Controller, 40V, 0,2A, 0..+70°: Hi-rel	16-DIP	NEC	-
µA494LMQB	Lin-IC	PWM Controller, 40V, 0,2A, 0..+70°: Hi-rel	20-LCC	NEC	-
µA494PV	Lin-IC	PWM Controller, 40V, 0,2A, -40..+85°	16-DIP	NEC	-
µA5116	CMOS-IC	Telecom, µ-Law Companding Codec	16-DIC	Fch	KT5116, M5116, MK5116, TP51
µA55107ADM(QB)	I/O-IC	2x Line Receiver	14-DIC	Fairchild	SN55107..
µA55110ADM(QB)	I/O-IC	2x Line Driver	14-DIC	Fairchild	SN55110..
µA55452BRM(QB)	I/O-IC	2x Interface Driver, NAND	8-DIC	Fch	-
µA555HM(QB)	Lin-IC	Timer, -55..+125°	81	Fch	-
µA555RM(QB)	Lin-IC	Timer, -55..+125°	8-DIC	Fch	-
µA555SC	Lin-IC	Timer, 0..+70°	8-MDIP	Fch	-
µA555TC	Lin-IC	Timer, 0..+70°	8-DIP	Fairchild	NE555..
µA556PC	Lin-IC	Dual, timer, 0..+70°	14-DIP	Fairchild	NE556..
µA565JJC, KJC	Lin-D/A-IC	12-bit, Hi-speed (30nS), 0..+70°	24-DIC	And	AD565..CS65D
µA565SJM, TJM	Lin-D/A-IC	12-bit, Hi-speed (30nS), -55..+125°	24-DIC	NEC	-
µA571JJC, KJC	A/D-IC	10-bit, 0..+70°	18-DIC	Fch	AD571, CS71D

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µA571SJM,SDM(QB)	Lin-A/D-IC	10-bit,-55..+125°	18-DIC	NEC	AD571,CS71D
µA5912	CMOS-IC	Telecom,PCMCODEC-Filter	16-DIC	Fch	ETC5040,KT3040,M5912,TP3
µA592DC,PC	Lin-IC	Video-amplifier90MHz,0..+70°	14-DIC,DIP	Fairchild	LM592,NE592F,N,NJM592D
µA592DM	Lin-IC	Video-amplifier90MHz,+125°	14-DIC	NEC	SE592F,J
µA592SC	Lin-IC	Video-amplifier90MHz,0..+70°	8-MDIP	NEC	NE592D8,NJM592M8,TL592D8
µA592TC	Lin-IC	Video-amplifier90MHz,0..+70°	8-DIP	NEC	NE592N8,NJM592D8,TL592BP
µA6685DM	Comp-IC	Hi-speed,±7V,2,7nS,-55..+125°	16-DIC	Fch	-
µA6685DV,PV	Comp-IC	Hi-speed,±7V,2,7nS,-30..+85°	16-DIC,DIP	Fch	-
µA6685HM	Comp-IC	Hi-speed,±7V,2,7nS,-55..+125°	82	Fch	-
µA6685HV	Comp-IC	Hi-speed,±7V,2,7nS,-30..+85°	82	Fch	AM6685..
µA6685SV	Comp-IC	Hi-speed,±7V,2,7nS,-30..+85°	14-MDIP	Fch	-
µA6687DM	Comp-IC	Hi-speed,±7V,2,7nS,-55..+125°	16-DIC	Fch	-
µA6687DV,PV	Comp-IC	Hi-speed,±7V,2,7nS,-30..+85°	16-DIC,DIP	Fch	AM6687..
µA685DM	Comp-IC	Hi-speed,±7V,3nS,-55..+125°	16-DIC	Fch	-
µA685DV,PV	Comp-IC	Hi-speed,±7V,3nS,-30..+85°	16-DIC,DIP	Fch	-
µA685HM	Comp-IC	Hi-speed,±7V,3nS,-55..+125°	82	Fch	-
µA685HV	Comp-IC	Hi-speed,±7V,3nS,-30..+85°	82	Fch	AM685..MC685..
µA685SV	Comp-IC	Hi-speed,±7V,3nS,-30..+85°	14-MDIP	Fch	-
µA687(A)DM	Comp-IC	Dual,±7V,<8nS,-55..+125°	16-DIC	Fch	-
µA687(A)DV,PV	Comp-IC	Dual,±7V,<8nS,-30..+85°	16-DIC,DIP	Fch	AM687..
µA702DC,DM(QB)	Op-IC	GenP,Series712,+14/-7V,0..+70°(DM=-55..+125°)	14-DIC	Fairchild	-
µA702FM(QB)	Op-IC	GenP,Series712,+14/-7V,-55..+125°	10-FLT	Fch	-
µA702HC	Op-IC	GenP,Series712,+14/-7V,0..+70°	81	Fch	-
µA702HM(QB)	Op-IC	GenP,Series712,+14/-7V,-55..+125°	81	Fch	-
µA703C	Lin-IC	FM-IF	8-DIP	Fch	SN76603
µA709(A)DM(QB)	Op-IC	GenP,Series109,±18V,:Hi-rel,-55..+125°	14-DIC	Fairchild	-
µA709(A)FM(QB)	Op-IC	GenP,Series109,±18V,:Hi-rel,-55..+125°	10-FLP	Fch	-
µA709(A)HM(QB)	Op-IC	GenP,Series109,±18V,0..+70°	81	Fch	-
µA709HC	Op-IC	GenP,Series109,±18V,0..+70°	81	Fch	-
µA709PC,CN	Op-IC	GenP,Series109,±18V,0..+70°	14-DIP	Fch,Tix	-
µA7095C,CD	Op-IC	GenP,Series109,±18V,0..+70°	8-MDIP	Fch,Tix	-
µA709TC,CP	Op-IC	GenP,Serles109,±18V,0..+70°	8-DIP	Fch,Tix	-
µA710DC,PC	Comp-IC	Hi-speed,+14/-7V,10mA,0..+70°	14-DIC,DIP	Fairchild	-
µA710DM(QB)	Comp-IC	Hi-speed,+14/-7V,10mA,-55..+125°	14-DIC	Fairchild	-
µA710FM(QB)	Comp-IC	Hi-speed,+14/-7V,10mA,-55..+125°	10-FLP	Fch	-
µA710HC	Comp-IC	Hi-speed,+14/-7V,10mA,0..+70°	81	Fch	-
µA710HM(QB)	Comp-IC	Hi-speed,+14/-7V,10mA,-55..+125°	81	Fch	-
µA711DC,PC	Comp-IC	Dual,Hi-speed,+14/-7V,50mA,0..+70°	14-DIC,DIP	Fairchild	-
µA711DM(QB)	Comp-IC	Dual,Hi-speed,+14/-7V,50mA,-55..+125°	14-DIC	Fairchild	-
µA711FM(QB)	Comp-IC	Dual,Hi-speed,+14/-7V,50mA,-55..+125°	10-FLP	Fch	-
µA711HC	Comp-IC	Dual,Hi-speed,+14/-7V,50mA,0..+70°	82	Fch	-
µA711HM(QB)	Comp-IC	Dual,Hi-speed,+14/-7V,50mA,-55..+125°	82	Fch	-
µA714(E,L)HC	Op-IC	Lo-offset(<250µV),±22V,0,6MHz,0..70°	81	Fch	OP-07..NJMOP07..
µA714(L)SC	Op-IC	Lo-offset(<250µV),±22V,0,6MHz,0..70°	8-MDIP	Fch	-
µA714(L)TC	Op-IC	Lo-offset(<250µV),±22V,0,6MHz,0..70°	8-DIP	Fch	-
µA714HM(QB)	Op-IC	Lo-offset(<250µV),±22V,0,6MHz,-55..+125°	81	Fch	-
µA715DC,DM	Op-IC	Lo-offset(<250µV),±22V,0,6MHz,0..70°	14-DIC	Fairchild	-
µA715HC	Op-IC	Hi-speed,±18V,100V/µS,0..70°	82	Fch	-
µA715HM(QB)	Op-IC	Hi-speed,±18V,100V/µS,-55..+125°	82	Fch	-
µA723CD,CN	VR-IC	+2..37V,0,15A,0..+70°	14-DIC,DIP	NEC	-
µA723CD,SC	VR-IC	+2..37V,0,15A,0..+70°	14-MDIP	Phi,Fch	-
µA723CF,CN,DC,PC	VR-IC	+2..37V,0,15A,0..+70°	14-DIC,DIP	Phi,Fch	-
µA723CL,HC	VR-IC	+2..37V,0,15A,0..+70°	82	Phi,Fch	723..
µA723F	VR-IC	+2..37V,0,15A,0..+70°	14-SOP	NEC	-
µA723F,N,DM(QB)	VR-IC	+2..37V,0,15A,-55..+125°	14-DIC,DIP	Phi,Fch	-
µA723HM(QB)	VR-IC	+2..37V,0,15A,-55..+125°	82	Fch	-
µA723LMQB	VR-IC	+2..37V,0,15A,-55..+125°	20-LCC	Fch	-
µA725(A)HM(QB)	Op-IC	GenP,Series725,±22V,-55..+125°	81	Fch	-
µA725(E)HC	Op-IC	GenP,Series725,±22V,0..+70°	81	Fch	-
µA725TC	Op-IC	GenP,Series725,±22V,0..+70°	8-DIP	Fch	-
µA727HC	Op-IC	Preamplifier,±18V,0..+70°	82	Fch	-
µA727HM	Op-IC	Preamplifier,-55..+150°	82	NEC	-
µA732C	Lin-IC	Stereo-Decoder	-	Fch	MC1304,SN76104
µA733C,HC	Lin-IC	DifferentialVideo-Amplifier,90MHz,±8V,0..+70°	82	Phi,Fch	HA17733M,LM733CH

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µA733CF,CN,DC,PC	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, 0..+70°	14-DIC,DIP	Phi,Fch	HA17733(G,P),KA733CN,LM733
µA733CN	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, 0..+70°	14-DIP	NEC	-
µA733F,N,DM(QB)	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, -55..+125°	14-DIC,DIP	Phi,Fch	-
µA733FM(QB)	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, -55..+125°	14-FLP	Fch	-
µA733HC(QB)	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, -55..+12°	82	Fch	LM733H
µA733N	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, -55..+125°	14-DIP	NEC	-
µA733SC	Lin-IC	Differential Video-Amplifier, 90MHz, ±8V, 0..+70°	14-MDIP	Fch	KA733CD
µA734DC	Comp-IC	±15V, 200nS, 0..+70°	14-DIP	Fairchild	-
µA734DM	Comp-IC	±15V, 200nS, -55..+150°	14-DIP	NEC	-
µA734HC	Comp-IC	=µA734DC:	82	NEC	-
µA734HM	Comp-IC	=µA734DC: -55..+150°	82	NEC	-
µA7392DV,PV	Lin-IC	DC Motor Speed Control	14-DIC,DIP	Fairchild	-
µA739C	Op-IC	Dual, Lo-noise, ±18V, 0..+70°	14-DIP	Fairchild	TBA231
µA741(A)DM(QB)	Op-IC	GenP, Series 741, ±18 (A=±22)V, -55..+125°	14-DIC	Fairchild	-
µA741(A)FM(QB)	Op-IC	=µA741HC: -55..+125°, A=±22V	10-FLP	Fch	-
µA741(A)HM(QB)	Op-IC	=µA741HC: -55..+125°, A=±22V	81	Fch	-
µA741(A)RM(QB)	Op-IC	=µA741HC: -55..+125°, A=±22V	8-DIC	Fch	-
µA741(E)HC,CL	Op-IC	GenP, Series 741, ±18 (E=±22)V, 0..+70°	81	Fch,Tix	-
µA741(E)RC,TC	Op-IC	=µA741(E)HC: Fig. →	8-DIC,DIP	Fch	-
µA741CF,CN,CP	Op-IC	=µA741HC: Fig. →	8-DIC,DIP	Phi,Tix	-
µA741DC	Op-IC	GenP, Series 741, ±18, 0..+70°	14-DIP	Fairchild	-
µA741F,N	Op-IC	=µA741CH: ±22V, -55..+125°	8-DIC,DIP	Phi	-
µA741SC,CD	Op-IC	=µA741HC: SMD	8-MDIP	Fch,Phi,Tix	-
µA747(A)DM(QB)	Op-IC	=µA747HC: -55..+125°, A=±22V	14-DIC	Fch	-
µA747(A)FM(QB)	Op-IC	=µA747HC: -55..+125°, A=±22V	14-FLP	Fch	-
µA747(A)HM(QB)	Op-IC	=µA747HC: -55..+125°, A=±22V	82	Fch	-
µA747(E)DC,PC	Op-IC	=µA747HC: Fig. →	14-DIC,DIP	Fch	-
µA747(E)HC,CL	Op-IC	Dual, Series 747, ±18 (A=±22)V, 0..+70°	82	Fch,Tix	-
µA747C	Op-IC	Dual, Series 747, ±18 (A=±22)V, 0..+70°	14-DIP	NEC	-
µA747CF,CN	Op-IC	=µA747HC: Fig. →	14-DIC,DIP	Phi,Tix	-
µA747F,N	Op-IC	=µA747CL: ±22V, -55..+125°	14-DIC,DIP	Phi	-
µA747SC,CD	Op-IC	GenP, Series 748, ±22V, 0..+70°	14-MDIP	Fch,Phi,Tix	-
µA748CL,CT	Op-IC	GenP, Series 748, ±18V, 0..+70°	81	Tix,Phi	-
µA748CN,DC	Op-IC	GenP, Series 748, ±18V, 0..+70°	14-DIP,DIC	Tix,Fch	-
µA748CP,CV	Op-IC	GenP, Series 748, ±18V, 0..+70°	8-DIP	Tix,Phi	-
µA748HC	Op-IC	GenP, Series 748, ±22V, 0..+70°	81	Fch	-
µA748HM,T	Op-IC	=µA748HC: -55..+125°	81	Fch,Phi	-
µA748RC,TC	Op-IC	=µA748HC: Fig. →	8-DIP	Fch	-
µA748SC	Op-IC	=µA748HC: SMD	8-MDIP	Fch	-
µA75107(A,B)DC,PC	I/O-IC	2x Line Receiver	14-DIC,DIP	Fairchild	DS75107..MC75107..SN7510
µA75107(A,B)SC	I/O-IC	2x Line Receiver	14-MDIP	NEC	-
µA75108BPC	I/O-IC	2x Line Receiver	14-DIP	Fairchild	DS75108..MC75108..SN7510
µA75108BSC	I/O-IC	2x Line Receiver	14-MDIP	NEC	-
µA75110ADC,APC	I/O-IC	2x Line Driver	14-DIC,DIP	Fairchild	HD75110,SN75110..
µA75110ASC	I/O-IC	2x Line Driver	14-MDIP	NEC	-
µA75150PC	I/O-IC	2x Line Driver	14-DIP	NEC	DS75150N,SN75150..
µA75150RC,TC	I/O-IC	2x Line Driver	8-DIC,DIP	Fch	DS75150J8
µA75150SC	I/O-IC	2x Line Driver	8-MDIP	NEC	-
µA75154DC,PC	I/O-IC	4x Line Receiver for RS232	16-DIC,DIP	Fch	DS75154,HD75154,KA2653,SN
µA75450DC,PC	I/O-IC	2x Interface Driver, positive AND	14-DIC,DIP	Fairchild	DS75450..HD75450A..SN754
µA75451RC,TC	I/O-IC	2x Interface Driver, positive AND	8-DIC,DIP	Fch	HD75451A..SG75451..SN754
µA75451SC	I/O-IC	2x Interface Driver, positive AND	8-MDIP	NEC	-
µA75452SC	I/O-IC	2x Interface Driver, positive NAND	8-MDIP	NEC	-
µA75452TC	I/O-IC	2x Interface Driver, positive NAND	8-DIP	Fch	HD75452..SG75452..SN7545
µA75453SC	I/O-IC	2x Interface Driver, positive OR	8-MDIP	NEC	-
µA75453TC	I/O-IC	2x Interface Driver, positive OR	8-DIP	Fairchild	HD75453..SG75453..SN7545
µA75461RC,TC	I/O-IC	2x Interface Driver, positive AND	8-DIC,DIP	Fch	SG75461,SN75461
µA75462TC	I/O-IC	2x Interface Driver, positive NAND	8-DIP	Fch	SG75462,SN75462
µA75471RC,TC	I/O-IC	2x Interface Driver, positive AND	8-DIC,DIP	Fch	SN75471
µA75472TC	I/O-IC	2x Interface Driver, positive NAND	8-DIP	Fch	SN75472
µA75491PC	I/O-IC	MOS to LED 4-Segm. Interface Driver	14-DIP	Fairchild	DS75491..MC75491..SN7549
µA75492PC	I/O-IC	MOS to LED 6-Segm. Interface Driver	14-DIP	Fairchild	MC75492..SN75492..
µA758A,C,DC,N,P..	Lin-IC	PLL-FM-Stereo-Decoder	16-DIP	Fch,Mot	CA758,MC1311,SN76116,LM1
µA759HC	Op-IC	Power, ±18V, 325mA, 0..+125°	81	Fch	-

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µA759HM(QB)	Op-IC	=µA759HC:-55..+150°	81	Fch	-
µA759U1C	Op-IC	=µA759HC:Fig.→	13/4Pin	Fch	-
µA760DM,DC(QB)	Comp-IC	=µA760HC:(RM=-55..+125°),Fig.→	14-DIC	Fch	-
µA760HC	Comp-IC	Hi-speed,±8,10mA,0..+70°	81	Fch	LM160..LM260..LM360..
µA760HM(QB)	Comp-IC	=µA760HC:-55..+125°	81	Fch	-
µA760RM,RC	Comp-IC	=µA760HC:(RM=-55..+125°),Fig.→	8-DIC	Fch	-
µA77000U1C	Op-IC	=µA759HC:250mA	13/4Pin	Fch	µA759U1C
µA7702DC,DM(QB)	Op-IC	=µA702HC:(DM=-55..+125°),Fig.→	14-DIC	Fch	-
µA771(A,B,L)RC,TC	Op-IC	JFET,±18V,13V/µS,3MHz,0..+70°	8-DIC,DIP	Fch	-
µA771(A,B,L)SC	Op-IC	=µA771..RC,TC:SMD	8-MDIP	Fch	-
µA771ARM,BRM(QB)	Op-IC	=µA771..RC,TC:-55..+125°	8-DIC	Fch	-
µA771BHM(QB)	Op-IC	=µA771..RC,TC:-55..+125°	81	Fch	-
µA772	Op-IC	=µA771..:Dual	-	Fch	-
µA774..DC,PC	Op-IC	=µA771..RC,TC:Quad	14-DIC,DIP	Fch	-
µA774..DM	Op-IC	=µA771..RM:Quad	14-DIC	Fch	-
µA774..SC	Op-IC	=µA771..SC:Quad	14-MDIP	Fch	-
µA776HC	Op-IC	Lo-power,±18V,0,8V/µS,0..+70°	81	Fch	-
µA776HM(QB)	Op-IC	=µA776HC:-55..+125°	81	Fch	-
µA776TC	Op-IC	=µA776HC:Fig.→	8-DIP	Fch	-
µA7805..24CKA,CKC	VR-IC	+5..24V,1,5A,0..+125°	23a	TI	78xx..(TO-3)
µA7805..7824(C)DA	VR-IC	+5..24V,1A,-55..+125°,C=0..+125°	23a	Philips	78xx..(TO-3)
µA7805..7824KC	VR-IC	+5..24V,1A,0..+150°	23a	Fairchild	78xx..(TO-3)
µA7805..7824KM(QB)	VR-IC	=µA7805..7824KC:-55..+150°	23a	Fch	-
µA7805..7824UC,CU	VR-IC	+5..24V,1A,0..+85/150°	17b	Fch,Phi	78xx..(TO-220)
µA78GU1C	VR-IC	+5..+30V,1A,0..+150°	13(MEQReg)	Fch	-
µA78L05..82ASC	VR-IC	=µA78L..AWC:SMD	8-MDIP	NEC	-
µA78L05..82AWC	VR-IC	+5..+15V,0,1A,0..+125°	7b	Fairchild	78Lxx..(TO-92)
µA78L05..82AWV	VR-IC	=µA78L..AWC:-40..+125°	7b	NEC	-
µA78M..HM(QB)	VR-IC	=µA78..HC:-55..+150°	2e	Fch	-
µA78M..LMQB	VR-IC	=µA78..HC:Hi-rel,-55..+150°	20-LCC	Fch	-
µA78M05..24HC	VR-IC	+5..24V,0,5A,0..+150°	2e	Fairchild	78Mxx..(TO-5/39)
µA78M05..24UC	VR-IC	+5..24V,0,5A,0..+150°	17b	Fairchild	78Mxx..(TO-220)
µA78MGU1C	VR-IC	+5..+30V,0,5A,0..+150°	13(MEQReg)	Fch	-
µA78S40DC,PC	Lin-IC	Sw-Reg,1,25..40V,1,5A,0..+70°	16-DIC,DIP	Fch,Mot	KA78S40
µA78S40DM,DMQB	Lin-IC	=µA78S40DC,PC:-55..+125°	16-DIC	Fch,Mot	-
µA78S40PV	Lin-IC	=µA78S40DC,PC:-40..+125°	16-DIP	Fch	-
µA7905..24CKA,CKC	VR-IC	-5..-24V,1,5A,0..125°	23d	TI	79xx..(TO-3)
µA7905..7924KC	VR-IC	-5..-24V,1A,0..+150°	23d	Fairchild	79xx..(TO-3)
µA7905..7924KM(QB)	VR-IC	=µA7905..7824KC:-55..+150°	23d	Fch	-
µA7905..7924UC	VR-IC	-5..-24V,1A,0..+150°	17c	Fairchild	79xx..(TO-220)
µA798SC	Op-IC	=µA798TC:SMD	8-MDIP	Fch	-
µA798TC	Op-IC	Dual,±18V,0,6V/µS,1MHz,0..+70°	8-DIP	Fch	-
µA79GU1C	VR-IC	-2,2..-30V,1A,0..+150°	13(MRegQE)	Fch	-
µA79M..HM(QB)	VR-IC	=µA79..HC:-55..150ш	2f	Fch	-
µA79M..LMQB	VR-IC	=µA79..HC:Hi-rel,-55..+150°	20-LCC	Fch	-
µA79M05..24HC	VR-IC	-5..-15V,0,5A,0..+150°	2f	Fairchild	79xx..(TO-5/39)
µA79M05..24UC	VR-IC	-5..-15V,0,5A,0..150°	17c	Fairchild	79xx..(TO-220)
µA79MGU1C	VR-IC	-2,2..-30V,0,5A,0..+150°	13(MRegQE)	Fch	-
µA9614DC,PC	I/O-IC	2x Differential Line Driver,0..+70°	16-DIC,DIP	Fch	SN75114..
µA9614DM(QB)	I/O-IC	=µA9614DC,PC:-55..+125°	16-DIC	Fch	-
µA9614FM(QB)	I/O-IC	=µA9614DC,PC:-55..+125°	16-FLP	Fch	-
µA9614LM(QB)	I/O-IC	=µA9614DC,PC:-55..+125°	20-LCC	Fch	-
µA9615DC,PC	I/O-IC	2x Differential Line Receiver,0..+70°	16-DIC,DIP	Fch	SN75115..
µA9615DM(QB)	I/O-IC	=µA9615DC,PC:-55..+125°	16-DIC	Fch	-
µA9615FM(QB)	I/O-IC	=µA9615DC,PC:-55..+125°	16-FLP	Fch	-
µA9615LM(QB)	I/O-IC	=µA9615DC,PC:-55..+125°	20-LCC	Fch	-
µA9616HDM(QB)	I/O-IC	3x Line Driver for RS232,V.24	14-DIC	Fairchild	-
µA9616HLM(QB)	I/O-IC	=µA9616HDM:Fig.→	20-LCC	NEC	-
µA96172DC,PC	I/O-IC	4x Diff. Line Driver for RS422A/485	16-DIC,DIP	Fch	AM26LS31, SN75172
µA96173DC,PC	I/O-IC	4x Diff. Line Rcv. for RS422A/423A/485	16-DIC,DIP	Fch	AM26LS32, SN75173
µA96174DC,PC	I/O-IC	4x Diff. Line Driver for RS422A/485	16-DIC,DIP	Fch	MC3487
µA96175DC,PC	I/O-IC	4x Diff. Line Rcv. for RS422A/423/485	16-DIC,DIP	Fch	MC3486
µA96176RC,TC	I/O-IC	Differential Bus Transceiver for RS422A/485	8-DIC,DIP	Fch	-
µA96177RC,TC	I/O-IC	Differential Bus Repeater for RS422A/485	8-DIC,DIP	Fch	-

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µA96178RC,TC	I/O-IC	Differential Bus Repeater for RS422A/485	8-DIC,DIP	Fch	-
µA9622DM(QB)	I/O-IC	2x Line Receiver	14-DIC	Fairchild	-
µA9622FM(QB)	I/O-IC	2x Line Receiver	14-FLP	NEC	-
µA9622LM(QB)	I/O-IC	2x LIne Receiver	20-LCC	NEC	-
µA9624DM(QB)	I/O-IC	2x TTL, MOS Interface Element	14-DIC	Fairchild	-
µA9624FM(QB)	I/O-IC	2x TTL, MOS Interface Element	14-FLP	NEC	-
µA9625DM(QB)	I/O-IC	2x TTL, MOS Interface Element	14-DIC	Fairchild	-
µA9625FM(QB)	I/O-IC	2x TTL, MOS Interface Element	14-FLP	NEC	-
µA9627DM(QB)	I/O-IC	2x Line Receiver for RS232	16-DIC	Fch	-
µA9636ARC,ATC	I/O-IC	2x Progr. Line Drv. for RS-423, 0..+70°	8-DIC,DIP	Fch	MC3488
µA9636ARM(QB)	I/O-IC	2x Progr. Line Drv. for RS-423, 0..+70°	8-DIC	NEC	-
µA9637ARC,ATC	I/O-IC	2x Line Receiver for RS422, 423, 0..+70°	8-DIC,DIP	Fch	-
µA9637ARM(QB)	I/O-IC	2x Line Receiver for RS422, 423, -55..+125°	8-DIC	NEC	-
µA9637ASC	I/O-IC	2x Line Receiver for RS422, 423, 0..+70°	8-MDIP	NEC	-
µA9638RC,TC	I/O-IC	2x Line Drv. for RS422, Hi-speed, 0..+70°	8-DIC,DIP	Fch	-
µA9638RM(QB)	I/O-IC	2x Line Drv. for RS422, Hi-speed, -55..+125°	8-DIC	NEC	-
µA9638SC	I/O-IC	2x Line Drv. for RS422, Hi-speed, 0..+70°	8-MDIP	NEC	-
µA9639ARM(QB)	I/O-IC	2x Line Receiver for RS422, 423, 232, -55..+125°	8-DIC	NEC	-
µA9639ATC	I/O-IC	2x Line Receiver for RS422, 423, 232, 0..+70°	8-DIP	Fairchild	-
µA9640DC,PC	I/O-IC	4x Bus Transceiver, 0..+70°	16-DIC,DIP	Fch	AM26S10..
µA9640DM	I/O-IC	4x Bus Transceiver, -55..+125°	16-DIC	Fch	-
µA9643TC	I/O-IC	2x TTL to MOS/CCD Driver, 0..70°	8-DIP	Fairchild	-
µA9645DC,PC	I/O-IC	4x TTL to MOS/CCD Driver, 0..70°	16-DIC,DIP	Fch	i3245
µA96501DC	Lin-IC	4-bit Current Source, ±0,01%	16-DIC	Fch	-
µA96502DC	Lin-IC	4-bit Current Source, ±0,05%	16-DIC	Fch	-
µA96503DC	Lin-IC	4-bit Current Source, ±0,2%	16-DIC	Fch	-
µA9665DC,PC	Lin-IC	7x NPN-Darl, 50V, 0,5A, 0..+70°	16-DIC,DIP	Fch	ULN2001A
µA9666DC,PC	Lin-IC	7x NPN-Darl, 50V, 0,5A, 0..+70° Int. R1=10,5kΩ, 7V-Z-Di	16-DIC,DIP	Fch	→ULN2002A
µA9666DM	Lin-IC	7x NPN-Darl, 50V, 0,5A, -55..+125°	16-DIC	NEC	-
µA9667DC,PC	Lin-IC	7x NPN-Darlington-Array, 50V, 0,5A, Int. R1=2,7kΩ	16-DIC,DIP	Fch	→ULN2003A
µA9667DM(QB)	Lin-IC	7x NPN-Darlington-Array, 50V, 0,5A, Int. R1=2,7kΩ, -55..+125°	16-DIC	NEC	-
µA9668DC,PC	Lin-IC	7x NPN-Darlington-Array, 50V, 0,5A, Int. R1=10,5kΩ	16-DIC,DIP	Fch	→ULN2004A
µA9668DM	Lin-IC	7x NPN-Darlington-Array, 50V, 0,5A, Int. R1=10,5kΩ, -55..+125°	16-DIC	NEC	-
µA9679TC	I/O-IC	Differential Bus Transceiver for RS422A	8-DIP	Fairchild	-
µA9708	A/D-IC	A/D-Converter, 6 channels	16-DIP	Fch	MB4053, MC14443
µAV22DC,PC	CMOS-IC	Telecom, full duplex modem, V.22	28-DIC,DIP	Fch	-
µAV22QC	CMOS-IC	Telecom, full duplex modem, V.22	28-MDIP	NEC	-
µPA101B	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-FLP	Nec	-
µPA101G	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	8-MDIP	NEC	-
µPA102B	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-FLP	Nec	-
µPA102G	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-MDIP	NEC	-
µPA103B	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-FLP	Nec	-
µPA103G	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-MDIP	NEC	-
µPA104B	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-FLP	Nec	-
µPA104G	Lin-IC	NPN-Trans. Array, UHF, 15V, 40mA, 9GHz	14-MDIP	NEC	-
µPA1424H	Lin-IC	4x NPN, Hi-beta, 60V, ±2A, 3,5W, B>1000	10-SIP	Nec	-
µPA1426H	Lin-IC	4x NPN-Darl, 150/80V, ±2A, 3,5W, B>2000	10-SIP	Nec	-
µPA1427H	Lin-IC	4x PNP-Darl, 80/80V, ±2A, 3,5W, B>2000	10-SIP	Nec	-
µPA1428AH	Lin-IC	4x NPN-Darl, 60/60V, ±2A, 3,5W, B=2k..20k	10-SIP	NEC	-
µPA1428H	Lin-IC	4x NPN-Darl, 60/60V, ±2A, 3,5W, B>2000	10-SIP	Nec	-
µPA1434H	Lin-IC	4x NPN, Hi-beta, Lo-sat, 60V, 3A, B>800	10-SIP	Nec	-
µPA1436AH	Lin-IC	4x NPN, Hi-beta, Lo-sat, 60V, ±3/5A, 0,3/1,9µS, B>800	10-SIP	Nec	-
µPA1436H	Lin-IC	4x NPN-Darl, 150/100V, ±3/6A, B>2000	10-SIP	Nec	-
µPA1437H	Lin-IC	4x PNP-Darl, 100/100V, ±3/6A, B>2000	10-SIP	Nec	-
µPA1438H	Lin-IC	4x NPN-Darl, Z-Di, 100/100V, ±3A, B>2000	10-SIP	Nec	-
µPA1452H	Lin-IC	4x NPN, Lo-sat, 60V, 5A, 3,5W	10-SIP	Nec	-
µPA1453H	Lin-IC	4x PNP, Lo-sat, 60V, 5A, 3,5W	10-SIP	Nec	-
µPA1454H	Lin-IC	4x NPN, Hi-beta, 100V, 5A, 3,5W, B>800	10-SIP	Nec	-
µPA1456H	Lin-IC	4x NPN-Darl, 150/100V, ±5A, 3,5W, B>2000	10-SIP	Nec	-
µPA1457H	Lin-IC	4x PNP-Darl, 100/100V, ±5A, 3,5W, B>2000	10-SIP	Nec	-
µPA1458H	Lin-IC	4x NPN-Darl, Z-Di, 60/60V, ±5A, B>2000	10-SIP	Nec	-
µPA1476H	Lin-IC	4x NPN-Darl, Z-Di, 100/100V, ±2A, B>2000	10-SIP	Nec	-
µPA1478H	Lin-IC	4x NPN-Darl, Z-Di, 31/31V, ±2A, B>2000	10-SIP	Nec	-
µPA1500	MOS-N-FET-e*	2x 2V-MOS, LogL, 60V, ±3A, 4W, <0,18Ω	12-SIP	Nec	-

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µPA1501	MOS-N-FET-e*	2x2V-MOS,LogL,120V,±3A,4W,<55mΩ	12-SIP	Nec	-
µPA1520H	MOS-N-FET-e	2x2V-MOS,LogL,30V,±2A,3,5W,<0,17Ω	10-SIP	Nec	-
µPA1522H	MOS-N-FET-e	2x2V-MOS,LogL,60V,±2A,3,5W,<0,25Ω	10-SIP	Nec	-
µPA1523H	MOS-P-FET-e	2x2V-MOS,LogL,60V,±2A,3,5W,<0,8Ω	10-SIP	Nec	-
µPA1524H	MOS-N-FET-e	2x2V-MOS,LogL,80V,±2A,3,5W,<0,8Ω	10-SIP	Nec	-
µPA1526H	MOS-N-FET-e	2x2V-MOS,LogL,100V,±2A,3,5W,<0,4Ω	10-SIP	Nec	-
µPA1527H	MOS-P-FET-e	2x2V-MOS,LogL,100V,±2A,3,5W,<1Ω	10-SIP	Nec	-
µPA1552H	MOS-N-FET-e	2x2V-MOS,LogL,60V,±5A,3,5W,<0,3Ω	10-SIP	Nec	-
µPA1556H	MOS-N-FET-e	2x2V-MOS,LogL,100V,±5A,3,5W,<0,45Ω	10-SIP	Nec	-
µPA1570H	MOS-N-FET-e	2x2V-MOS,LogL,30V,±2A,3,5W,<0,35Ω	10-SIP	Nec	-
µPA1572H	MOS-N-FET-e	2x2V-MOS,LogL,60V,±2A,3,5W,<0,6Ω	10-SIP	Nec	-
µPA1576H	MOS-N-FET-e	2x2V-MOS,LogL,100V,±2A,3,5W,<1,2Ω	10-SIP	Nec	-
µPA15A	Si-NPN	Dual,25V,0,05A,2x0,3W,200MHz	81bt	Nec	-
µPA16	Si-NPN	2 Dr,Chopper,15/10V,50mA,B>20	81	Nec	-
µPA1600CX	MOS-IC	8xMOS-N-FET,30V,0,5A,1W,-40..+85°	20-DIP	Nec	-
µPA1600GS	MOS-IC	8xMOS-N-FET,30V,0,5A,1W,-40..+85°	20-MDIP	Nec	-
µPA1601CX	MOS-IC	7xMOS-N-FET,30V,0,43A,1W,-40..+85	16-DIP	Nec	-
µPA1601GS	MOS-IC	7xMOS-N-FET,30V,0,43A,1W,-40..+85	16-MDIP	Nec	-
µPA1602CX	MOS-IC	7xMOS-N-FET,30V,0,43A,1W,-40..+85	16-DIP	Nec	-
µPA1602GS	MOS-IC	7xMOS-N-FET,30V,0,43A,1W,-40..+85	16-MDIP	Nec	-
µPA1603CX	MOS-IC	4xMOS-N-FET,30V,0,87A,1W,-40..+85°	16-DIP	Nec	-
µPA1604CX	MOS-IC	4xMOS-N-FET,30V,0,87A,1W,-40..+85°	16-DIP	Nec	-
µPA1640GS	MOS-IC	8x2 Input AND Gate,-40..+85°	20-MDIP	Nec	-
µPA1700(A)	MOS-N-FET-e*	V-MOS,LogL,30V,±7A,<27mΩ(3,5A)	8-MDIP/ca1	Nec	-
µPA1701	MOS-N-FET-e*	V-MOS,LogL,30V,±7A,<40mΩ(3,5A)	8-MDIP/ca1	Nec	-
µPA1702	MOS-N-FET-e*	V-MOS,LogL,30V,±8A,<15mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1703	MOS-N-FET-e*	V-MOS,LogL,30V,±10A,<11mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1704	MOS-N-FET-e*	V-MOS,LogL,30V,±10A,<16mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1705	MOS-N-FET-e*	V-MOS,LogL,30V,±8A,<40mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1706	MOS-N-FET-e*	V-MOS,LogL,30V,±13A,<12mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1707	MOS-N-FET-e*	V-MOS,LogL,30V,±10A,<21mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1708	MOS-N-FET-e*	V-MOS,LogL,40V,c7A,<40mΩ(3,5A)	8-MDIP/ca1	Nec	-
µPA1709	MOS-N-FET-e*	V-MOS,LogL,40V,c9A,<20mΩ(4,5A)	8-MDIP/ca1	Nec	-
µPA1710	MOS-P-FET-e*	V-MOS,LogL,30V,±6A,<70mΩ(2,5A)	8-MDIP/ca1	Nec	-
µPA1711	MOS-P-FET-e*	V-MOS,LogL,30V,±7A,<70mΩ(3,5A)	8-MDIP/ca1	Nec	-
µPA1712	MOS-P-FET-e*	V-MOS,LogL,30V,±8A,<48mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1715	MOS-P-FET-e*	V-MOS,LogL,30V,±16A,<18mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1716	MOS-P-FET-e*	V-MOS,LogL,30V,±8A,<26mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1717	MOS-P-FET-e*	V-MOS,LogL,30V,±6A,<59mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1720	MOS-N-FET-e*	V-MOS,LogL,30V,±8A,<38mΩ(5A)	8-MDIP/ca2	Nec	-
µPA1721	MOS-N-FET-e*	V-MOS,LogL,30V,±10A,<17mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1722	MOS-N-FET-e*	V-MOS,LogL,30V,±9A,<32mΩ(4,5A)	8-MDIP/ca1	Nec	-
µPA1723	MOS-N-FET-e*	V-MOS,LogL,20V,±13A,<8,7mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1724	MOS-N-FET-e*	V-MOS,LogL,20V,±10A,<15mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1725	MOS-N-FET-e*	V-MOS,LogL,20V,±7A,<30mΩ(3,5A)	8-MDIP/ca1	Nec	-
µPA1726	MOS-N-FET-e*	V-MOS,LogL,20V,±12A,<13mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1727	MOS-N-FET-e*	V-MOS,LogL,60V,±10A,<25mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1728	MOS-N-FET-e*	V-MOS,LogL,60V,±9A,<35mΩ(4,5A)	8-MDIP/ca1	Nec	-
µPA1730	MOS-P-FET-e*	V-MOS,LogL,30V,±13A,<15mΩ(6,5A)	8-MDIP/ca1	Nec	-
µPA1731	MOS-P-FET-e*	V-MOS,LogL,30V,±10A,<22mΩ(5A)	8-MDIP/ca1	Nec	-
µPA1750	MOS-P-FET-e*	V-MOS,Dual,LogL,20V,±3,5A,<0,18Ω(1,8A),120/570nS	8-MDIP/ca3	Nec	-
µPA1751	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±5A,<37mΩ(2,5A)	8-MDIP/ca3	Nec	-
µPA1752	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±5A,<46mΩ(2,5A)	8-MDIP/ca3	Nec	-
µPA1753	MOS-N-FET-e*	V-MOS,Dual,LogL,20V,±6A,<30mΩ(3A),180/630nS	8-MDIP/ca3	Nec	-
µPA1754	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±7A,<53mΩ(3,5A),110/189nS	8-MDIP/ca3	Nec	-
µPA1755	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±7A,<45mΩ(3,5A),146/859nS	8-MDIP/ca3	Nec	-
µPA1756	MOS-N-FET-e*	V-MOS,Dual,LogL,20V,±6A,<40mΩ(3A),535/2250nS	8-MDIP/ca3	Nec	-
µPA1757	MOS-N-FET-e*	V-MOS,Dual,LogL,20V,±7A,<32mΩ(3,5A),263/1408nS	8-MDIP/ca3	Nec	-
µPA1758	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±6A,<40mΩ(3,5A),240/1040nS	8-MDIP/ca3	Nec	-
µPA1759	MOS-N-FET-e*	V-MOS,Dual,LogL,60V,±5A,<0,24Ω(2,5A),56/130nS	8-MDIP/ca3	Nec	-
µPA1760	MOS-N-FET-e*	V-MOS,Dual,LogL,30V,±8A,<42mΩ(4A),160/80nS	8-MDIP/ca3	Nec	-
µPA1763	MOS-N-FET-e*	V-MOS,Dual,LogL,60V,±4,5A,<66mΩ(2,3A),51/62nS	8-MDIP/ca3	Nec	-
µPA1764	MOS-N-FET-e*	V-MOS,Dual,LogL,60V,±7A,<46mΩ(3,5A),589/530nS	8-MDIP/ca3	Nec	-
µPA1770	MOS-P-FET-e*	V-MOS,Dual,LogL,20V,±6A,<59mΩ(3A),135/270nS	8-MDIP/ca3	Nec	-

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µPA1790	MOS-P/N-FET-e	N+P-V-MOS,LogL,60V,N:±1A,<340mΩ(0,5A),P:±0,7A	8-MDIP/ca3	Nec	-
µPA1792	MOS-P/N-FET-e	N+P-V-MOS,LogL,30V,N:±6,8A,<42mΩ(3,4A),P:±5,8A	8-MDIP/ca3	Nec	-
µPA1800	MOS-N-FET-e*	V-MOS,LogL,30V,±5A,<39mΩ(3A),88/86nS	8-SSMDIP/	Nec	-
µPA1801	MOS-N-FET-e*	V-MOS,LogL,20V,±6A,<25mΩ(3A),125/190nS	8-SSMDIP/	Nec	-
µPA1802	MOS-N-FET-e*	V-MOS,LogL,20V,±7A,<25mΩ(3,5A),270/1410nS	8-SSMDIP/	Nec	-
µPA1803	MOS-N-FET-e*	V-MOS,LogL,30V,±8A,<16mΩ(4A),104/119nS	8-SSMDIP/	Nec	-
µPA1804	MOS-N-FET-e*	V-MOS,LogL,30V,±8A,<32mΩ(4A),107/75nS	8-SSMDIP/	Nec	-
µPA1810	MOS-P-FET-e*	V-MOS,LogL,12V,±4A,<100mΩ(2A),140/160nS	8-SSMDIP/	Nec	-
µPA1811	MOS-P-FET-e*	V-MOS,LogL,20V,±4A,<80mΩ(2A),140/150nS	8-SSMDIP/	Nec	-
µPA1812	MOS-P-FET-e*	V-MOS,LogL,30V,±5A,<69mΩ(2,5A),190/190nS	8-SSMDIP/	Nec	-
µPA1813	MOS-P-FET-e*	V-MOS,LogL,12V,±5A,<40mΩ(2,5A),209/1920nS	8-SSMDIP/	Nec	-
µPA1814	MOS-P-FET-e*	V-MOS,LogL,30V,±7A,<27mΩ(3,5A),170/183nS	8-SSMDIP/	Nec	-
µPA1815	MOS-P-FET-e*	V-MOS,LogL,20V,±7A,<19mΩ(3,5A),245/300nS	8-SSMDIP/	Nec	-
µPA1852	MOS-N-FET-e*	V-MOS,Dual,LogL,20V,±6A,<60mΩ(3A),215/740nS	8-SSMDIP/ca4	Nec	-
µPA1853	MOS-P-FET-e*	V-MOS,Dual,LogL,30V,±2,5A,<180mΩ(1,5A),280/1420nS	8-SSMDIP/ca4	Nec	-
µPA1854	MOS-P-FET-e*	V-MOS,Dual,LogL,12V,±3A,<105mΩ(1,5A),542/2240....nS	8-SSMDIP/ca4	Nec	-
µPA1855	MOS-N-FET-e*	V-MOS,Dual,LogL,20V,±6A,<29mΩ(3A),333/1139nS	8-SSMDIP/ca4	Nec	-
µPA1856	MOS-P-FET-e*	V-MOS,Dual,LogL,20V,±4,5A,<77mΩ(2,5A),828/940nS	8-SSMDIP/ca4	Nec	-
µPA1890	MOS-P/N-FET-e	N+P-V-MOS,LogL,30V,N:±6A,<47mΩ(3A),P:±5A,<64mΩ(2,5A)	8-SSMDIP/ca4	Nec	-
µPA1900	MOS-N-FET-e*	V-MOS,LogL,20V,±5,5A,<45mΩ	46bn4	Nec	-
µPA1910	MOS-P-FET-e*	V-MOS,LogL,12V,±2,5A,<130mΩ	46bn4	Nec	-
µPA1911	MOS-P-FET-e*	V-MOS,LogL,20V,±2,5A,<190mΩ	46bn4	Nec	-
µPA1912	MOS-P-FET-e*	V-MOS,LogL,12V,±4,5A,<70mΩ	46bn4	Nec	-
µPA1913	MOS-P-FET-e*	V-MOS,LogL,20V,±4,5A,<90mΩ	46bn4	Nec	-
µPA1914	MOS-P-FET-e*	V-MOS,LogL,30V,±4,5A,<96mΩ	46bn4	Nec	-
µPA1915	MOS-P-FET-e*	V-MOS,LogL,20V,±4,5A,<90mΩ	46bn4	Nec	-
µPA2001C	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W	16-DIP	Nec	-
µPA2001GR	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W	16-MDIP	Nec	-
µPA2002C	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=10,5kΩ,Z-Di-Input	16-DIP	Nec	-
µPA2002GR	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=10,5kΩ,Z-Di-Input	16-MDIP	Nec	-
µPA2003C	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=2,7kΩ	16-DIP	Nec	-
µPA2003GR	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=2,7kΩ	16-MDIP	Nec	-
µPA2004C	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=10,5kΩ	16-DIP	Nec	-
µPA2004GR	Lin-IC	7xNPN-Darl.,60V,0,5A,0,9W,R1=10,5kΩ	16-MDIP	Nec	-
µPA2981C	Lin-IC	8xNPN-Darl.,50V,0,5A,1,4W,R1=3kΩ	18-DIP	Nec	-
µPA2982C	Lin-IC	8xNPN-Darl.,50V,0,5A,1,4W,R2=8,5kΩ	18-DIP	Nec	-
µPA2987GS	Lin-IC	7xNPN-Darl.,50V,0,5A,0,65W,R1=3kΩ	16-MDIP	Nec	-
µPA33A	MOS-P-FET-e	Dual,Chopper,30V,20mA,2x0,1W	81cc	Nec	-
µPA34A	MOS-N-FET-d	Dual,Chopper,30V,10mA,2x0,1W	81cc	Nec	-
µPA36A	Si-NPN	Dual,7V,0,05A,0,2W,B=50>20	81bf1	Nec	-
µPA37A	Si-NPN	Dual,25V,0,08A,0,3W,B=110>50	81bt	Nec	-
µPA38A	Si-NPN	Dual,60V,0,05A,0,6W,B=550>300	81bt	Nec	-
µPA39A	Si-NPN	Dual,60V,0,05A,0,6W,B=500>300	81bt	Nec	-
µPA44D	Lin-IC	16-Di-Array,60V,0,5A,0,5W,<25nS	14-DIP	NEC	-
µPA46D	Lin-IC	4xNPN-Trans.,80V,1A,1,5W,350MHz	14-DIP	NEC	-
µPA47D	Lin-IC	4xNPN-Trans.,80V,1A,1,5W,350MHz	14-DIP	NEC	-
µPA48D	Lin-IC	4xNPN-Trans.,90V,1A,1,5W,320MHz	14-DIP	NEC	-
µPA49A	Si-PNP	Dual,60V,0,05A,0,6W,B=150>80	81bt	Nec	-
µPA500T	Si-NPN	Dual,60V,0,1A,250MHz	45ba1	Nec	-
µPA501T	Si-PNP	Dual,60V,0,1A,180MHz	45ba1	Nec	-
µPA502T	MOS-N-FET-e	V-MOS,Dual,50V,0,1A,<25Ω(10mA)	45bb1	Nec	-
µPA503T	MOS-P-FET-e	V-MOS,Dual,50V,0,1A,<60Ω(10mA)	45bb1	Nec	-
µPA504T	Si-P/N	PNP+NPN,60V,0,1A,180/250MHz	45ba1	Nec	-
µPA505T	MOS-P/N-FET-e	V-MOS,P+N-FET,50V,0,1A,<60/25Ω	45bb1	Nec	-
µPA50A	N-FET	3xFET,60V,Idss>1,5mA,Up<2,4V	82	Nec	-
µPA53C	Lin-IC	5xNPN-Darl.,30V,0,4A,1,2W,B>2000	14-DIP	NEC	-
µPA54H,HA	Lin-IC	6xDi,75V,0,1A,0,5W,<3nS	7-SIP	Nec	-
µPA56C	Lin-IC	7xNPN-Trans.,60V,0,1A,0,55W,320MHz	16-DIP	Nec	-
µPA570T	Si-NPN	Dual,60V,0,1A,250MHz	45(2mm)	Nec	→?PA570T
µPA571T	Si-PNP	Dual,60V,0,1A,180MHz	45(2mm)	Nec	→?PA571T
µPA572T	MOS-N-FET-e	V-MOS,Dual,30V,±0,1A,<8Ω(10mA)	45bb1(2mm)	Nec	-
µPA573T	MOS-P-FET-e	V-MOS,Dual,30V,±0,1A,<25Ω(10mA)	45bb1(2mm)	Nec	-
µPA574T	Si-P/N	PNP+NPN,60V,0,1A,180/250MHz	45(2mm)	Nec	→?PA574T
µPA57C	Lin-IC	6xNPN-Darlington,40V,0,4A,1,5W,B>1000	14-DIP+h	Nec	-

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µPA600T	Si-NPN	Dual,60V,0,1A,250MHz	46	Nec	→?PA600T
µPA601T	Si-PNP	Dual,60V,0,1A,180MHz	46	Nec	→?PA601T
µPA602T	MOS-N-FET-e*	V-MOS,Dual,50V,0,1A,<25Ω(10mA)	46	Nec	→?PA602T
µPA603T	MOS-N-FET-e	V-MOS,Dual,50V,0,1A,<60Ω(10mA)	46	Nec	→*PA603T
µPA604T	Si-NPN	Dual,60V,0,1A,250MHz	46	Nec	→*PA604T
µPA605T	Si-PNP	Dual,60V,0,1A,180MHz	46	Nec	→?PA605T
µPA606T	MOS-N-FET-e	V-MOS,Dual,50V,0,1A,<25Ω(10mA)	46bn3	Nec	-
µPA607T	MOS-P-FET-e	V-MOS,Dual,50V,0,1A,<60Ω(10mA)	46bn3	Nec	-
µPA608T	Si-P/N	PNP:25V,0,5A,NPN:60V,0,1A	46bh1	Nec	-
µPA609T	Si-P/N	PNP+NPN,60V,0,5A,200/150MHz	46bl2	Nec	-
µPA60A	N-FET	Dual,40V,0,05A,Idss>0,5mA,Up<2,5V	81bx	Nec	-
µPA610TA	MOS-P-FET-e*	V-MOS,Dual,LogL,30V,±0,1A,<60Ω	46bn2	Nec	-
µPA6118C	Lin-IC	8xNPN-Darl.,85V,40mA,1,4W,R1=37kΩ	18-DIP	Nec	-
µPA611TA	MOS-P-FET-e*	V-MOS,Dual,LogL,30V,±0,1A,<15Ω	46bn2	Nec	-
µPA61A	N-FET	Dual,40V,0,05A,Idss>0,5mA,Up<2,5V	81bx	Nec	-
µPA62C	N-FET	Dual,HF-Mix,20V,Idss>8mA,Up<2,2V	8-DIP	Nec	-
µPA63H	N-FET	Dual,60V,30mA,Idss>1,5mA,Up<4,2V	7-SIP/bp	Nec	-
µPA64HA	Lin-IC	6xDi,75V,0,1A,0,5W,<8nS	7-SIP	Nec	-
µPA670T	Si-NPN	Dual,60V,0,1A,250MHz	46(2mm)	Nec	→*PA670T
µPA671T	Si-PNP	Dual,60V,0,1A,180MHz	46(2mm)	Nec	→?PA671T
µPA672T	MOS-N-FET-e	V-MOS,Dual,50V,0,1A,<20Ω(10mA)	46bn3(2mm)	Nec	-
µPA673T	Si-NPN	Dual,40V,0,2A,500MHz,12/25nS	46bh3(2mm)	Nec	-
µPA674T	Si-P/N	NPN:40V,0,2A,PNP:15V,0,05A	46bh1(2mm)	Nec	→?PA674T
µPA67C	Lin-IC	6xNPN-Darlington,30V,0,07A,0,55W	14-DIP	NEC	-
µPA68H	N-FET	Dual,50V,Idss>1mA,Up<2,5V	7-SIP/bp	Nec	-
µPA70A	N-FET	Dual,40V,0,05A,Idss>0,5mA,Up<2,5V	84bn	Nec	-
µPA71A	N-FET	Dual,40V,0,05A,Idss>0,5mA,Up<2,5V	84bn	Nec	-
µPA74V	Lin-IC	2xNPN-Trans.,80V,0,05A,2x0,3W	9-SQP	Nec	-
µPA75V	Lin-IC	2xPNP-Trans.,80V,0,05A,2x0,3W	9-SQP	Nec	-
µPA76V	Lin-IC	2xNPN-Trans.,60V,0,05A,2x0,3W	9-SQP	Nec	-
µPA77V	Lin-IC	2xPNP-Trans.,60V,0,05A,2x0,3W	9-SQP	Nec	-
µPA79C	Lin-IC	7xNPN-Darl.,20V,0,15A,0,55W,B>1000	16-DIP	Nec	-
µPA800T	Si-NPN	Dual,VHF/UHF,20V,35mA,8000MHz	46(2mm)	Nec	→?PA800T
µPA801T	Si-NPN	Dual,VHF/UHF,20V,0,1A,4500MHz	46bh3(2mm)	Nec	-
µPA801T-FB	Si-NPN	-	46(2mm)	Nec	→?PA801T
µPA801T-GB	Si-NPN	-	46(2mm)	Nec	→?PA801T
µPA802T	Si-NPN	=2x2SC4227	46bh3(2mm)	Nec	-
µPA802T-FB	Si-NPN	-	46(2mm)	Nec	→?PA802T
µPA802T-GB	Si-NPN	-	46(2mm)	Nec	→?PA802T
µPA803T	Si-NPN	=2x2SC4570	46bh3(2mm)	Nec	-
µPA803T-FB	Si-NPN	-	46(2mm)	Nec	→?PA803T
µPA803T-GB	Si-NPN	-	46(2mm)	Nec	→?PA803T
µPA804T	Si-NPN	=2x2SC4571	46bh3(2mm)	Nec	-
µPA804T-FB	Si-NPN	-	46(2mm)	Nec	→?PA804T
µPA804T-GB	Si-NPN	-	46(2mm)	Nec	→?PA804T
µPA805T	Si-NPN	-	46(2mm)	Nec	→?PA805T
µPA806T	Si-NPN	-	46(2mm)	Nec	→?PA806T
µPA807T	Si-NPN	-	46(2mm)	Nec	→?PA807T
µPA808T	Si-NPN	-	46(2mm)	Nec	→?PA808T
µPA809T	Si-NPN	-	46(2mm)	Nec	→?PA809T
µPA80C	Lin-IC	7xNPN+PNP-Trans,60V,0,05A,0,55W,B>250	16-DIP	Nec	-
µPA80GR	Lin-IC	7xNPN+PNP-Trans,60V,0,05A,0,55W,B>250	16-MDIP	Nec	-
µPA810T	Si-NPN	=2x2SC4226	46bl1(2mm)	Nec	-
µPA810T-FB	Si-NPN	-	46(2mm)	Nec	→?PA810T
µPA810T-GB	Si-NPN	-	46(2mm)	Nec	→?PA810T
µPA811T	Si-NPN	=2x2SC4228	46bl1(2mm)	Nec	-
µPA811T-FB	Si-NPN	-	46(2mm)	Nec	→?PA811T
µPA811T-GB	Si-NPN	-	46(2mm)	Nec	→?PA811T
µPA812T	Si-NPN	=2x2SC4227	46bl1(2mm)	Nec	-
µPA812T-FB	Si-NPN	-	46(2mm)	Nec	→?PA812T
µPA812T-GB	Si-NPN	-	46(2mm)	Nec	→?PA812T
µPA813T	Si-NPN	=2x2SC4570	46bl1(2mm)	Nec	-
µPA813T-FB	Si-NPN	-	46(2mm)	Nec	→?PA813T
µPA813T-GB	Si-NPN	-	46(2mm)	Nec	→?PA813T

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µPA814T	Si-NPN	-	46(2mm)	Nec	→?PA814T
µPA81C	Lin-IC	7xNPN-Darl.,45V,0,4A,0,8W,B>1000	16-DIP	Nec	-
µPA821TF	Si-NPN	-	46(2mm)	Nec	→?PA821TF
µPA826TF	Si-NPN	-	46(2mm)	Nec	→?PA826TF
µPA827TF	Si-NPN	-	46(2mm)	Nec	→?PA827TF
µPA828TF	Si-NPN	-	46(2mm)	Nec	→?PA828TF
µPA82C	Lin-IC	7xNPN+PNP-Trans,150V,0,05A,0,9W,B>250	18-DIP	Nec	-
µPA831TF	Si-NPN	-	46(2mm)	Nec	→?PA831TF
µPA832TF	Si-NPN	-	46(2mm)	Nec	→?PA832TF
µPA833TF	Si-NPN	-	46(2mm)	Nec	→?PA833TF
µPA834TF	Si-NPN	-	46(2mm)	Nec	→?PA834TF
µPA835TF	Si-NPN	-	46(2mm)	Nec	→?PA835TF
µPA836TF	Si-NPN	-	46(2mm)	Nec	→?PA836TF
µPB1003GS	Digi/Lin-IC	Telecom,GPS,HF/IF,PLL,synthesizer	30-SSMDIP	Nec	-
µPB1004GS	Digi/Lin-IC	Telecom,GPS,HF/IF,PLL,synthesizer	30-SSMDIP	Nec	-
µPB1010BGR	Digi-IC	TV/VC-Tuner Synth.,80..1300MHz	16-SSMDIP	Nec	-
µPB1011BGR	Digi-IC	TV/VC-Tuner Synth.,80..1300MHz	16-MDIP	NEC	-
µPB1012BGR	Digi-IC	TV/VC-Tuner Synth.,80..1300MHz	16-SSMDIP	Nec	-
µPB1013BGR	Digi-IC	TV/VC-Tuner Synth.,80..1300MHz	16-MDIP	NEC	-
µPB10142D	ECL-RAM-IC	64x1Bit,<25nS,-30..+85°	16-DIC	Nec	MC(M)10142
µPB10144D	ECL-RAM-IC	256x1Bit,<25nS,-30..+85°	16-DIC	Nec	MC10144,..10414..
µPB10148D	ECL-RAM-IC	64x1Bit,<25nS,-30..+85°	16-DIC	Nec	MC(M)10148
µPB1502GR	Digi-IC	Frequency-Divider:64/65,:128/129,1,7GHz	8-MDIP	Nec	-
µPB1502GR1	Digi-IC	Frequency-Divider:64/65,:128/129,2GHz	-	NEC	-
µPB1504GR	Digi-IC	Frequency-Divider:64/65,:128/129,1,1GHz	8-MDIP	Nec	-
µPB1505GR	Digi-IC	BS/CS,Frequency-Divider:256,:128,:64,3GHz	8-MDIP	Nec	-
µPB1506GV	Digi-IC	BS/CS,Frequency-Divider:256,:128,:64,3GHz	8-SSMDIP	Nec	-
µPB1507GV	Digi-IC	BS/CS,Frequency-Divider:256,:128,:64,3GHz	8-SSMDIP	Nec	-
µPB1508GV	Digi-IC	BS/CS,Frequency-divider,3GHz,:2	8-SSMDIP	Nec	-
µPB1509GV	Digi-IC	Frequency-Divider:2,:4,:8,1GHz	8-SSMDIP	Nec	-
µPB1510GV	Digi-IC	Frequency-Divider,1GHz,:4	8-SSMDIP	Nec	-
µPB2089D	TTL-RAM-IC	16x4-bit,<60nS,-25..+75°	16-DIC	Nec	i3101,..74S189..
µPB2200D	TTL-RAM-IC	256x1Bit,<50nS,-25..+75°	16-DIC	Nec	i3106,..74S200..
µPB2202D	TTL-RAM-IC	256x1Bit,<65nS,-25..+75°	16-DIC	Nec	i3106,..74S200..
µPB2205D	TTL-RAM-IC	1024x1Bit,<50nS,-25..+75°	16-DIC	Nec	..93L415..93415..
µPB2206D	TTL-RAM-IC	256x1Bit,<50nS,-25..+75°	16-DIC	Nec	74L301..74S301..93411
µPB2289D	TTL-RAM-IC	16x4-bit,<35nS,-25..+75°	16-DIC	Nec	i3101A,..74S189..
µPB243D	TTL-IC	DualTTL→MOSInterface,0..+75°	14-DIC	NEC	-
µPB249D	TTL-IC	FLT-Decoder/Driver,Ucc=7V,-25..+75°	16-DIC	Nec	-
µPB403C,D(-1,-2)	TTL-PROM-IC	256x4-bit,<60..35nS,-25..+75°	16-DIP,DIC	Nec	i3603,IM5603..
µPB405C,D(-1,-2)	TTL-PROM-IC	512x8-bit,<60..40nS,-25..+75°	24-DIP,DIC	Nec	i3604,IM5605,HM7640..
µPB406C,D(-1..-3)	TTL-PROM-IC	1024x4-bit,<70..35nS,-25..+75°	18-DIP,DIC	Nec	i3605,IM56S06,HM7642..
µPB409	TTL-PROM-IC	2048x8-bit,<50nS,-25..+75°	24-DIP,DIC	Nec	-
µPB425C,D(-1,-2)	TTL-PROM-IC	512x8-bit,<60..40nS,-25..+75°	24-DIP,DIC	Nec	i3624,IM5625,HM7641..
µPB426C,D(-1..-3)	TTL-PROM-IC	1024x4-bit,<70..35nS,-25..+75°	18-DIP,DIC	Nec	i3625,IM56S26,HM7643..
µPB429	TTL-PROM-IC	2048x8-bit,<50nS,-25..+75°	24-DIP,DIC	Nec	-
µPB450	Logic-IC	FPLA(Fieldprogr.Logic),9216Bit	48-DIP	Nec	-
µPB551C	Digi-IC	Frequency-Divider,150MHz,:10/11	-	Nec	-
µPB552C	Digi-IC	Frequency-Divider,150MHz,:10/11	-	Nec	-
µPB553AC	Digi-IC	Frequency-Divider,150MHz,:16	8-DIP	Nec	-
µPB554C	Digi-IC	Frequency-Divider,150MHz,:10/11	-	Nec	-
µPB555C	Digi-IC	Frequency-Divider,150MHz,:8/9	-	Nec	-
µPB556C	Digi-IC	Frequency-Divider,150MHz,:16	-	Nec	-
µPB562C	Digi-IC	Frequency-Divider,1GHz,:126/136	-	Nec	-
µPB571C	Digi-IC	Frequency-Divider,500MHz,:64/65	-	Nec	-
µPB572C	Digi-IC	Frequency-Divider,500MHz,:80/81	-	Nec	-
µPB597CX	Digi-IC	Dual,Frequency-divider:64/65,:128/129,1GHz	8-DIP	Nec	-
µPB597GR	Digi-IC	Dual,Frequency-divider:64/65,:128/129,1GHz	8-MDIP	NEC	-
µPB8212C,D	TTL-I/O-IC	8-bitI/OPortforµPD8080	24-DIP,DIC	Nec	i8212
µPB8214C	TTL-IC	8LevelInterruptControlerforµPD8080	24-DIP	Nec	i8214
µPB8216C,D	TTL-IC	8-bitBusDriverforµPD8080	16-DIP,DIC	Nec	i8216
µPB8224C,D	TTL-IC	ClockGeneratorDriverforµPD8080	16-DIP,DIC	Nec	i8224
µPB8226C,D	TTL-IC	8-bitBusDriverforµPD8080	16-DIP,DIC	Nec	i8226
µPB8228C,D	TTL-IC	Systemcontroller,busdriver	28-DIP,DIC	Nec	i8228

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µPB8238C,D	TTL-IC	System controller, bus driver	28-DIP,DIC	Nec	i8238
µPB8282C,D	TTL-IC	8-bit Latches, 5MHz, 0..+70°	20-DIP,DIC	Nec	-
µPB8283C,D	TTL-IC	8-bit Latches, 5MHz, 0..+70°	20-DIP,DIC	Nec	-
µPB8284C,D	TTL-IC	Clock Driver, 5MHz, 0..+70°	18-DIP,DIC	Nec	-
µPB8286C,D	TTL-IC	8-bit Bus Transceivers, 5MHz, 0..+70°	20-DIP,DIC	Nec	-
µPB8287C,D	TTL-IC	8-bit Bus Transceivers, 5MHz, 0..+70°	20-DIP,DIC	Nec	-
µPB8288D	TTL-IC	Bus Controller, 5MHz, 0..+70°	20-DIC	Nec	-
µPC1001(H)	Lin-IC	AF Pamp, 17V, 2,5A, 4,5W(13V/4Ω)	10-SIL	Nec	-
µPC1004C	Lin-IC	FM-IF, Ucc=6..15V	14-DIP	NEC	-
µPC1006C	Lin-IC	Tachometer, Ucc=10..16V	8-DIP+h	Nec	-
µPC1008C	Lin-IC	Phase-/Frequency-Detector, Ucc=7V	14-DIP	NEC	-
µPC1009C	Lin-IC	Sensor for 4 Key + LED-Indicator	20-DIP	Nec	-
µPC1013C	Lin-IC	AM-Tuner, AM/FM-IF	16-DIP	Nec	-
µPC1016C	Lin-IC	2x AF-Preamplifier, LN, Ucc=±12V	14-DIP	NEC	-
µPC1017G	Lin-IC	AF-Preamplifier, Ucc=3V	10-MDIP	Nec	-
µPC1018C,H	Lin-IC	AM-Tuner, AM/FM-IF, Ucc=2,5..6V	16-DIP	Nec	-
µPC1020(H)	Lin-IC	AF Pamp, 12V, 2,5A, 5,2W(13V/4Ω)	10-SIL	Nec	-
µPC1021(H)	Lin-IC	AM-Tuner, IF, AGC, Ucc=13V	14-DIP	NEC	-
µPC1023(H)	Lin-IC	AF-Preamplifier, Ucc=35V	7-SIP	Nec	µPC1024
µPC1024(H,H2)	Lin-IC	AF-Preamplifier, LN, Ucc=35V	7-SIP	Nec	µPC1023
µPC1025(H)	Lin-IC	AF Pamp, 17V, 2,5A, 4,8W(13V/4Ω)	10-SIL	Nec	-
µPC1026(C)	Lin-IC	FM Multiplex Stereo-Decoder	14-DIP	NEC	-
µPC1028(H)	Lin-IC	FM-IF + Demod., Ucc=10V	7-SIP	Nec	BA403, KA2245, LA1150, TA71
µPC1030(H)	Lin-IC	AF Pamp, 17V, 2,5A, 5,8W(13V/4Ω)	10-SIL	Nec	-
µPC1031(H,H2)	Lin-IC	CTV-Vertic.-Osc. + Output	10-SIL	Nec	KA2130A, LA1385, TA7242
µPC1032(H)	Lin-IC	2x AF-Preamp, LN, Ucc=13,2V	8-SIP	Nec	-
µPC1035(C)	Lin-IC	Recorder-Function control	14-DIP	NEC	-
µPC1037H,HA	Lin-IC	SSB-Amplifier	7-SIP	Nec	-
µPC103A	Lin-IC	Video-amplifier, 15V, 0,08A, 40MHz	83	Nec	-
µPC1042C	VR-IC	Sw-Reg Ctrl., Uref=5V, 0,1A, -20..+85°	16-DIP	Nec	-
µPC1043C	Lin-IC	Motor Controller	16-DIP	Nec	-
µPC1058C	Lin-IC	Motor Controller	16-DIP	Nec	-
µPC105A	Lin-IC	Video-amplifier, 20V, 0,08A, 40MHz	83ω	Nec	-
µPC1060C,D	VR-IC	2,5V ±1%, 10mA, -20..+70/80°	8-DIP,DIC	Nec	-
µPC1074A(GT)	VR-IC	+5V, µComp. Control, Watchdog	16-MDIP	Nec	-
µPC107A	Lin-IC	HF-Amp., 30V, 0,1A, 0..10MHz	83	Nec	-
µPC1093G	Vref-IC	2,495V ±%, 0,1A	8-MDIP	Nec	HA17431FP/FPA
µPC1093J	Vref-IC	2,495V ±%, 0,1A	7(KARef)	Nec	HA17431P/PA, TA76431S
µPC1093T	Vref-IC	2,495V ±%, 0,1A	39(KARef)	Nec	HA17431UA, TA76431F
µPC1094C	VR-IC	Sw-Reg Ctrl., Uref=5V, 0,1A, -20..+85°	14-DIP	NEC	-
µPC1094G	VR-IC	Sw-Reg Ctrl., Uref=5V, 0,1A, -20..+85°	14-MDIP	Nec	-
µPC1097V	Lin-IC	Solenoid driver, Ucc=8..16V	17/5Pin	Nec	-
µPC1099CX	VR-IC	Sw-Reg Ctrl., Uref=5V, 0,1A, -20..+85°	16-DIP	Nec	-
µPC1099GS	VR-IC	Sw-Reg Ctrl., Uref=5V, 0,1A, -20..+85°	16-MDIP	Nec	-
µPC11	Lin-IC	AF, Ucc=1,6..6V, 5mA, >55dB	10-FLP	Nec	-
µPC1100C	VR-IC	Dual Sw-Reg Control, Uref=2,5V, 25mA	16-DIP	Nec	-
µPC1100GS	VR-IC	Dual Sw-Reg Control, Uref=2,5V, 25mA	16-MDIP	Nec	-
µPC1104G	Lin-IC	Timer for el. Camera, Ucc=2,5V	10-FLP	Nec	-
µPC1150C	VR-IC	Dual Sw-Reg Control, Uref=2,5V, 25mA	16-DIP	Nec	-
µPC1150GS	VR-IC	Dual Sw-Reg Control, Uref=2,5V, 25mA	16-MDIP	Nec	-
µPC1154(H)	Lin-IC	AF Pamp, 17V, 2,5A, 4,8W(13V/4Ω)	10-SIL	Nec	-
µPC1155(H)	Lin-IC	AF Pamp, 17V, 2,5A, 5,5W(13V/4Ω)	10-SIL	Nec	-
µPC1156H,H2	Lin-IC	AF Pamp, 17V, 2,5A, 5,8W(13V/4Ω)	10-SIL	Nec	-
µPC1158H,H2	Lin-IC	Recorder-ALC, Ucc=2,2..15V	7-SIP	Nec	-
µPC1161C,C3	Lin-IC	FM Stereo-Decoder	16-DIP	Nec	µPC1235
µPC1163C,H	Lin-IC	FM-IF, Ucc=10..15V	7-SIP	Nec	-
µPC1165C	Lin-IC	Recorder, AF-Preamp + ALC	16-DIP+g	Nec	-
µPC1167C,C2	Lin-IC	FM-Dem + AFC + AGC	16-DIP	Nec	-
µPC1168C	Lin-IC	-	16-DIP	Nec	-
µPC1170	Lin-IC	Recorder, ALC	8-SIP	Nec	-
µPC1171C	Lin-IC	AM-HF + IF + AGC	14-DIP	NEC	-
µPC1173C	Lin-IC	FM Stereo-Decoder	16-DIP	Nec	-
µPC1176C	Lin-IC	FM-Noise suppressor	16-DIP	Nec	-
µPC1177	Lin-IC	AF Pamp, 10V, 2A, 3,5W(6V/4Ω)	12-SIL	Nec	-

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µPC1178C	Lin-IC	AM-Tuner+IF+AGC	16-DIP	Nec	-
µPC1180C	Lin-IC	Dolby B System	16-DIP	Nec	-
µPC1181H,H3	Lin-IC	AF Pamp, 5,8W(13V/4Ω)	7-SILP	Nec	-
µPC1182H,H3	Lin-IC	AF Pamp, 5,8W(13V/4Ω)	7-SILP	Nec	-
µPC1183(H)	Lin-IC	-		Nec	-
µPC1185H,H2	Lin-IC	2x AF Pamp, 2x5,8W(13V/4Ω)	12-SILP	Nec	-
µPC1186(H)	Lin-IC	2x AF-Preamp, LN	8-SIP	Nec	-
µPC1187V	Lin-IC	Stereo-Decoder	15-SQP	Nec	-
µPC1188H	Lin-IC	AF Pamp, ±30V, 5A, 18W(±22V/8Ω)	10-SILP	Nec	-
µPC1190C	Lin-IC	2x AF-Preamp, LN+Muting	16-DIP+g	Nec	-
µPC1191V	Lin-IC	AM-HF+IF+AGC	15-SQP	Nec	-
µPC1197C	Lin-IC	→KA2261	16-DIP	Nec	→KA2261
µPC1198H	Lin-IC	FM-IF	8-SIP	Nec	-
µPC1200V	Lin-IC	FM-IF+Quadrature Detector	15-SQP	Nec	-
µPC1204C	Lin-IC	Recorder-Rec/playback amplifier.	16-DIP	Nec	-
µPC1207H	Lin-IC	Audio Preamp., Low Noise, ±35V	8-SIP	Nec	-
µPC1208C	Lin-IC	FM-IF+AFC+AGC	16-DIP	Nec	µPC1167
µPC1210C	Lin-IC	Dolby B	16-DIP	Nec	-
µPC1211V	Lin-IC	PLL-FM-IF	19-SQP	Nec	-
µPC1212C	Lin-IC	AF Pamp, 3,5..V, 1W(6V/4Ω)	8-DIP+g	Nec	-
µPC1213C	Lin-IC	AF Pamp, 4,5..11V, 2,4W(9V/4Ω)	8-DIP+g	Nec	-
µPC1215V	Lin-IC	AM-Tuner, IF, AGC	19-SQP	Nec	KA22461
µPC1216V,V2	Lin-IC	AM-Tuner, IF, AGC	19-SQP	Nec	-
µPC1217(C)	Lin-IC	-	(20-DIP)	Nec	-
µPC1218H	Lin-IC	AF Pamp, 10V, 0,25W(3V/8Ω)	8-SIP	Nec	-
µPC121A	Lin-IC	2x Amplifier, Limiter	83	Nec	-
µPC1221C	Lin-IC	AF-Preamplifier, Pamp, 1W(6V)	14-DIP+g	Nec	-
µPC1222C	Lin-IC	AM-Tuner, AM/FM-IF+Demod.	16-DIP	Nec	-
µPC1223C	Lin-IC	Stereo-Decoder	22-DIP	Nec	-
µPC1224H	Lin-IC	2x AF-Amplifier, LN, ±22V	8-SIP	Nec	-
µPC1225H	Lin-IC	AF-driver, ±50V, 0,2A	12-SIL	Nec	µPC1270
µPC1226C	Lin-IC	AM-Tuner, PLL-Synthesizer	22-DIP	Nec	-
µPC1227V	Lin-IC	PLL FM MPX Stereo-Decoder	19-SQP	Nec	-
µPC1228H,HA	Lin-IC	2x AF-Preamp, LN, Ucc=6..16V	8-SIP	Nec	-
µPC1230H,H2	Lin-IC	AF Pamp, 25V, 4,5A, 20W(13V/4Ω)	12-SILP	Nec	-
µPC1232C	Lin-IC	Recorder-Rec/playback amplifier.	28-DIP	Nec	-
µPC1235C	Lin-IC	Stereo-Decoder	16-DIP	Nec	µPC1161
µPC1237H,HA	Lin-IC	AF-driver, Muting-Control	8-SIP	Nec	-
µPC1238H,V	Lin-IC	AF Pamp, ±18V, 4A, 12,5W(±13V/4Ω)	86/5Pin	Nec	TDA2030
µPC1241H	Lin-IC	AF Pamp, 18V, 4,5A, 9,2W(13V/2Ω)	8-SIL	Nec	-
µPC1242H	Lin-IC	AF Pamp, 18V, 4,5A, 9,2W(13V/2Ω)	8-SIL	Nec	-
µPC1243C	Lin-IC	AM-Tuner, HiFi	16-DIP	Nec	-
µPC1245V	Lin-IC	FM-IF+AGC+AFC	19-SQP	Nec	-
µPC1246C	Lin-IC	DC Motor-Driver, 3-phase	16-DIP	Nec	-
µPC1246G	Lin-IC	DC Motor-Driver, 3-phase	16-MDIP	Nec	-
µPC1248V	Lin-IC	AM-Tuner, IF, Demodulator, AGC	19-SQP	Nec	-
µPC1251C,D	Op-IC	=µPC358C: -20..+70/80°	8-DIP	Nec	-
µPC1251G,G2	Op-IC	=µPC358C: -20..+70°	8-MDIP	Nec	-
µPC1252H2,HA2	Lin-IC	Recorder, DBX-NR-System	8-SIP	Nec	-
µPC1253H2,HA2	Lin-IC	Recorder, DBX-NR-System, Level-Sensor	8-SIP	Nec	-
µPC1258V	Lin-IC	2x AF Pamp, 25V, 4,5A, 2x5,8W(13V/4Ω)	15-SQL	Nec	-
µPC1260G	Lin-IC	2x Headphone Amplifier	20-MDIP	Nec	-
µPC1263C	Lin-IC	→KA2214	14-DIP+g	Nec	KA2214
µPC1267C	Lin-IC	FM-IF	16-DIP	Nec	-
µPC1268H	Lin-IC	2x AF Pamp, 25V, 4,5A, 2x5,8W(13V/4Ω)	12-SILP	Nec	-
µPC1270H	Lin-IC	AF-driver, ±50V, 0,2A	12-SIL	Nec	µPC1225
µPC1274V	Lin-IC	AF Pamp, 25V, 4,5A, 20W(13V/4Ω)	15-SQL	Nec	-
µPC1277H	Lin-IC	-	12-SIL	Nec	-
µPC1278H	Lin-IC	2x AF Pamp, 20V, 2x2,5W(9V/4Ω)	12-SIL	Nec	-
µPC1280V	Lin-IC	AF Pamp, 18V, 4,5A, 20W(13V/4Ω)	12-SILP	Nec	-
µPC1284G	Lin-IC	Dolby B	20-MDIP	Nec	-
µPC1297CA	Lin-IC	2x Dolby HX PRO, Ucc=8..18V	18-DIP	Nec	-
µPC1298V	Lin-IC	AF-driver, ±60V, 0,25A	14-SQL	Nec	-
µPC12B	Lin-IC	AF Amplifier, Ucc=1,3V, >72dB	10-FLP	Nec	-

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µPC12G	Lin-IC	AF Amplifier, Ucc=6V, >75dB	10-FLP	Nec	-
µPC1308V	Lin-IC	AF Pamp, BTL, 25V, 4,5A, 15W(13V/4Ω)	14-SQL	Nec	-
µPC1310V	Lin-IC	2x AF Pamp, 25V, 4,5A, 2x5,8W(13V/4Ω)	14-SQL	Nec	-
µPC1313HA	Lin-IC	Recorder, 2x ALC, Ucc=6,5..15	9-SIP	Nec	-
µPC1316C	Lin-IC	2x AF Pamp, 18V, 2x2W(12V/8Ω)	14-DIP+g	Nec	-
µPC1318AV	Lin-IC	AF Pamp, BTL, 25V, 4,5A, 20W(13V/4Ω)	14-SQL	Nec	-
µPC1320C	Lin-IC	PLL FM MPX Stereo-Decoder	16-DIP	Nec	BA1320
µPC1321V	Lin-IC	AF Pamp, BTL, 16V, 4,5A, 20W(13V/4Ω)	15-SQL	Nec	-
µPC132D	Vref-IC	Reference-voltage, +4,3V, -4,3V	16-DIP	Nec	-
µPC1330GR	Lin-IC	=µPC1330HA: SMD	14-MDIP	Nec	-
µPC1330HA	Lin-IC	Recorder, 2x Head Switch	9-SIP	Nec	-
µPC1331V	Lin-IC	2x AF Pamp, 16V, 2x22W(9V/4Ω)	14-SQL	Nec	-
µPC1332V	Lin-IC	2x AF Pamp, 16V, 2x4W(12V/4Ω)	14-SQL	Nec	-
µPC1335V	Lin-IC	2x AF Pamp, 25V, 2x7W(15V/4Ω), BTL: 20W	14-SQL	Nec	-
µPC1342V	Lin-IC	AF-driver, ±70V, 0,25A	14-SQL	Nec	-
µPC1344GT	Lin-IC	AM-Tuner, for Car Radio	28-MDIP	Nec	-
µPC1346CS	Lin-IC	Radio Data System (RDS) Decoder	24-DIP	Nec	-
µPC1346GS	Lin-IC	=µPC1346: SMD	24-MDIP	Nec	-
µPC1348	Lin-IC	FM-IF, Stereo-MPX-Decoder, Dem.	-	Nec	-
µPC1350(C)	Lin-IC	AF-Preamplifier, Pamp, ALC, 0,45W(6V/8Ω)	14-DIP+g	Nec	-
µPC1351(C)	Lin-IC	CTV-PAL-Chroma	14-DIP	NEC	-
µPC1352C,C2	Lin-IC	CTV-NTSC-Decoder	28-DIP	Nec	-
µPC1353(C)	Lin-IC	TV-Sound-IF, + AF Pre-PA, 2,4W	14-DIP+g	Nec	KA2102A
µPC1356C,C2	Lin-IC	CTV-Video-IF + AGC(neg.), Dem.	22-DIP	Nec	-
µPC1358(H)	Lin-IC	CTV, VD-Output Amplifier, 14..20°, 90°	10-SIP	Nec	-
µPC1360C	Lin-IC	TV-Sensor for 16 Key + Indicator	24-DIP	Nec	-
µPC1361C	Lin-IC	TV-Sensor for 12 Key + Indicator	24-DIP	Nec	-
µPC1362C	Lin-IC	TV-Sensor for 12 Key + Indicator	20-DIP	Nec	-
µPC1363C,CA	Lin-IC	TV-Sensor for 16 Key + LED-Indicator	24-SDIP	Nec	-
µPC1364C,C2	Lin-IC	CTV-SECAM-Decoder	28-DIP	Nec	-
µPC1365C,C2,C3	Lin-IC	CTV-PAL-Decoder + Chroma + RGB-E	28-DIP	Nec	-
µPC1366C	Lin-IC	TV, Video-IF, pos. AGC	14-DIP+g	Nec	KA2912
µPC1367C	Lin-IC	CTV, Synchr. Signal	24-DIP	Nec	-
µPC1368H	Lin-IC	CTV, VD-Output Amplifier, 20..26°, 90°	12-SIP	Nec	-
µPC1373H	Lin-IC	IR-Remote Control Preamplifier	8-SIP	Nec	KA2181
µPC1374H	Lin-IC	IR-Remote Control Preamplifier	8-SIP	Nec	KA2183
µPC1377(C)	Lin-IC	CTV, Synchr.-Combi, Stabi, AFC	22-DIP	Nec	-
µPC1378H	Lin-IC	CTV, VD-Output Amplifier, 9..20°, 90..100°	7-SIP	Nec	-
µPC1379(C)	Lin-IC	TV, HD/VD-Synchr., VD-Output	16-DIP+g	Nec	KA2133
µPC1382C	Lin-IC	TV, Sound-IF, Demodulator	14-DIP	NEC	-
µPC1391(H,HA)	Lin-IC	TV-Sound-IF, Dem.	8-SIP	Nec	-
µPC1392H	Lin-IC	TV-Sound-IF, Dem.	8-SIP	Nec	-
µPC1394C	Lin-IC	TV, SMPS Controller	14-DIP	NEC	-
µPC1394G	Lin-IC	=µPC1394C: SMD	14-MDIP	Nec	-
µPC1397C	Lin-IC	CTV, RGB Analog Interface	22-DIP	Nec	-
µPC1401	Lin-IC	CTV, NTSC RGB-Signal, AFC, APC	42-SDIP	Nec	-
µPC1402(CA)	Lin-IC	CTV, NTSC RGB-Signal, AFC, APC	42-SDIP	Nec	-
µPC1406HA	Lin-IC	Dual-Attenuator/Potentiometer	9-SIP	Nec	-
µPC1410G	Lin-IC	Modulator, 2MHz, Ucc=4..5,5V	8-DIP	Nec	-
µPC1414	Lin-IC	→KA2913A	16-DIP	Nec	KA2913A, TA7678
µPC1416G	Lin-IC	TV, Sound-/Video-IF, AGC, AFT	28-MDIP	Nec	-
µPC1417CA	Lin-IC	CTV, RGB Interface	28-SDIP	Nec	-
µPC141A	VR-IC	4,5..30V, 0,05A, -20..+80°	81	Nec	-
µPC141C,D	VR-IC	=µPC141A: -20..+70/80°	8-DIP,DIC	Nec	(µPC305C)
µPC141G,G2	VR-IC	=µPC141A: -20..+70°	8-MDIP	Nec	(µPC305G)
µPC1420(CA)	Lin-IC	CTV, PAL/NTSC RGB-Signal, AFC, APC	48-SDIP	Nec	-
µPC1423(CA)	Lin-IC	CTV, PAL/NTSC RGB-Signal, AFC, APC	48-SDIP	Nec	-
µPC142A	VR-IC	-0,035..-30V, 0,05A, -20..+80°	82	Nec	µA104HM
µPC14305..14324HF	VR-IC	+5..24V, 1A, Iso	17b	NEC	78xx..(TO-220Iso)
µPC1447	Lin-IC	Motor Speed Control	14	Nec	-
µPC1458C	Op-IC	=µPC251C,D: 0..+70°	8-DIP	Nec	-
µPC1458G,G2	Op-IC	=µPC251C,D: 0..+70°	8-MDIP	Nec	-
µPC1470H	Lin-IC	DC Motor-Driver, Ucc=3,5..16V	14/4Pin	Nec	-
µPC1482G	Lin-IC	LCD-CTV, PAL/NTSC Video/Chroma	28-MDIP	Nec	-

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µPC1484CA	Lin-IC	VTR, Digital tuning interface (DTS)	18-SDIP	Nec	-
µPC1485CA	Lin-IC	VTR, PLL Digital Tuning Interface (DTS)	18-SDIP	Nec	-
µPC1486C	Lin-IC	TV, PLL Tuning Interface (DTS)	16-DIP	Nec	-
µPC1487C	Lin-IC	TV, PLL Tuning Interface (DTS)	16-DIP	Nec	-
µPC1488(H)	Lin-IC	TV-Vertical deflection	7/9-SIL	Nec	-
µPC1498H	Lin-IC	CTV, VD-Output Amplifier	8-SIL	Nec	-
µPC1507(A)C	Lin-IC	→KA2981	16-DIP	Nec	KA2981, TA7673
µPC151A	Op-IC	=µPC151C, D: -20..+80°	81	Nec	-
µPC151C, D	Op-IC	GenP, Series 741, ±18V, -20..+70/80°	8-DIP, DIC	Nec	-
µPC151G, G2	Op-IC	=µPC151C, D: SMD	8-MDIP	Nec	-
µPC1524A	Lin-IC	→KA2945	28-DIP	Nec	HA11745, KA2945
µPC152A	Op-IC	MOS-FET, Hi-ohm, ±18V, -20..+80°	81	Nec	-
µPC1534C	Lin-IC	→KA2944	28-DIP	Nec	HA11744, KA2944
µPC1536C	Lin-IC	→KA2988	28-DIP	Nec	HA11741, KA2988
µPC153A	Op-IC	Lo-power, ±18V, -20..+80°	81	Nec	-
µPC153D	Op-IC	=µPC153A: Fig. →	8-DIC	Nec	-
µPC154A	Op-IC	Hi-prec, Series 725, ±18V, -20..+80°	81	Nec	-
µPC154C, D	Op-IC	=µPC154A: -20..+70/80°	8-DIP, DIC	Nec	-
µPC1555C	Lin-IC	Timer, +18V, 0..70°C	8-DIP	NEC	LM555, NE555, TDB0555
µPC1555G, G2	Lin-IC	=µPC1555C: SMD	8-MDIP	NEC	NE555CH, CM, µPC617G
µPC156A	Op-IC	Hi-ohm Input, ±18V, -20..+80°	81	Nec	-
µPC156D	Op-IC	=µPC156A: Fig. →	8-DIC	Nec	-
µPC1571C	Lin-IC	Analog Compander, Ucc=6..16V, 0..+70°	16-DIP	Nec	-
µPC1571G	Lin-IC	=µPC1571C: SMD	16-MDIP	NEC	-
µPC157A	Op-IC	GenP, Series 101, ±18V, -20..+80°	81	Nec	-
µPC157C, D	Op-IC	=µPC157A: -20..+70/80uu	8-DIP, DIC	Nec	-
µPC159A	Op-IC	Hi-speed, ±20V, -20..+80°	81	Nec	-
µPC159C, D	Op-IC	=µPC159A: -20..+70/80°	8-DIP, DIC	Nec	(µPC318C)
µPC16305..16324HF.	VR-IC	=µPC16305H..16324H: Iso	17c	Nec	79xx..(TO-220Iso)
µPC1651G	Lin-IC	UHF-amplifier, 19dB/500MHz	6	Nec	-
µPC1652G	Lin-IC	UHF-amplifier, 18dB/500MHz	8-MDIP	Nec	-
µPC1653A	Lin-IC	UHF-amplifier, 18dB/500MHz	-	Nec	-
µPC1654A	Lin-IC	UHF-amplifier, 19dB/500MHz	-	Nec	-
µPC1655C	Lin-IC	UHF-amplifier, 18dB/500MHz	8-DIP	NEC	-
µPC1656C	Lin-IC	UHF-amplifier, 19dB/500MHz	8-DIP	NEC	-
µPC1658A	Lin-IC	=µPC1658C:	81	NEC	-
µPC1658C	Lin-IC	UHF-amplifier, 10GHz, Ucc<12V	8-DIP	NEC	-
µPC1658G	Lin-IC	=µPC1658C: SMD	8-MDIP	NEC	-
µPC1663C	Lin-IC	Video-amplifier, -45..+85°	8-DIP	NEC	-
µPC1663G	Lin-IC	=µPC1663C: c7V, -45..+75°	8-MDIP	NEC	-
µPC1663GV	Lin-IC	=µPC1663C: c7V, -45..+75°	8-SSMDIP	NEC	-
µPC1664C	Lin-IC	Video-amplifier, -45..+85°	14-DIP	NEC	-
µPC1668C	Lin-IC	Isolation IF, 10..150MHz, Ucc=8..11V	8-DIP	Nec	-
µPC1669C	Lin-IC	Isolation IF, 10..150MHz, Ucc=8..11V	8-DIP	Nec	-
µPC1670C	Lin-IC	Isolation IF, 10..150MHz, Ucc=8..11V	8-DIP	Nec	-
µPC1675G	Lin-IC	UHF-amplifier, 1,9GHz, 5V	44	Nec	-
µPC1676G	Lin-IC	UHF-amplifier, 1,2GHz, Ucc=5V	44	Nec	-
µPC1677C	Lin-IC	UHF-amplifier, 1,8GHz, Ucc=5V	8-DIP	NEC	-
µPC1678G	Lin-IC	UHF-amplifier, 2GHz, Ucc=5V	8-MDIP	Nec	-
µPC1678GV	Lin-IC	=µPC1678G:	8-SSMDIP	NEC	-
µPC1679G	Lin-IC	UHF-amplifier, 1,8GHz, 5V	8-MDIP	Nec	-
µPC1685G	Lin-IC	TV, UHF-Tuner, Ucc=5V	8-MDIP	Nec	-
µPC1686G	Lin-IC	VHF/CATV Converter, Ucc=5V	8-MDIP	Nec	-
µPC1686GV	Lin-IC	=µPC1686G:	8-SSMDIP	NEC	-
µPC1687G	Lin-IC	TV, UHF Converter, Ucc=5V	8-MDIP	Nec	-
µPC1687GV	Lin-IC	=µPC1687G:	8-SSMDIP	NEC	-
µPC1688G	Lin-IC	UHF-amplifier, 1,1GHz, Ucc=5V	44	Nec	-
µPC1694GR	Lin-IC	TV, CATV Converter, Ucc=5V	14-MDIP	NEC	-
µPC1701C	Lin-IC	Triac-zero volt. switch	8-DIP	NEC	KA2804
µPC1702H	Lin-IC	Thyristor-trigger control	8-SIP	Nec	-
µPC171D	MOS-IC	Memory Sense Amp., Ucc=7V, 0..+75°	14-DIC	NEC	-
µPC177C, D, ED	Comp-IC	Quad, Series 139, ±18V, -20..+70/80°	14-DIP, DIC	NEC	139..239..
µPC177G, G2	Comp-IC	=µPC177C, D, ED: SMD	14-MDIP	Nec	139...239..(µPC339G)
µPC1820A, ACT	Lin-IC	CTV, VTR, PLL Sound-/Video-IF, AGC, APC	30-SDIP	Nec	-

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µPC1823A,ACU	Lin-IC	CTV,VTR,PLL Sound-/Video-IF,I²C-bus	42-SDIP	Nec	-
µPC1830(GT)	Lin-IC	CTV,PAL/NTSC Video/Chroma	28-MDIP	Nec	-
µPC1851(CU)	Lin-IC	TV,Dual Sound Processor	42-SDIP	Nec	-
µPC1852A(GT)	Lin-IC	TV,Dual Sound Processor	28-MDIP	Nec	-
µPC1852B(CT)	Lin-IC	TV,Dual Sound Processor	28-SDIP	Nec	-
µPC1853(CT-..)	Lin-IC	Audio-Processor (Surround Sound)	30-SDIP	Nec	-
µPC1860GS	Lin-IC	TV,Digital (EDTV) Clock Gener.	36-SMDIP	Nec	-
µPC1862GS	Lin-IC	TV,Digital (EDTV) Clock Gener.	36-SMDIP	Nec	-
µPC1872AGH-03,-04	Lin-IC	=µPC1872(A)CU: SMD	48-MP	Nec	-
µPC1872CU,ACU-..	Lin-IC	TV,Dual Sound Processor	42-SDIP	Nec	-
µPC1874(CT)	Lin-IC	TV,Dual Sound Processor	28-SDIP	Nec	-
µPC1875(CT)	Lin-IC	TV,Dual Sound Processor	30-SDIP	Nec	-
µPC1881(CT)	Lin-IC	Monitor,Multisync Processor	30-SDIP	Nec	-
µPC1891A(CY)	Lin-IC	Audio-Processor (Surround Sound)	20-DIP	Nec	-
µPC1892(CT)(-02)	Lin-IC	Audio-Processor (Surround Sound)	30-SDIP	Nec	-
µPC1893(CS)	Lin-IC	CTV,NTSC Color+Y-Signal	22-SDIP	Nec	-
µPC1900CS	VR-IC	Sw-Reg Ctrl.,0,1A,500kHz	24-DIP	Nec	-
µPC1900GS	VR-IC	=µPC1900CS: SMD	24-MDIP	Nec	-
µPC1905CX	VR-IC	Sw-Reg Ctrl.,0,1A,500kHz	16-DIP	Nec	-
µPC1905GS	VR-IC	=µPC1905CS: SMD	16-MDIP	Nec	-
µPC1906CX	VR-IC	Sw-Reg Ctrl.,0,1A,500kHz	16-DIP	Nec	-
µPC1906GS	VR-IC	=µPC1906CS: SMD	16-MDIP	Nec	-
µPC1944GR	Vref-IC	=µPC1944J: SMD	8-MDIP	Nec	-
µPC1944J	Vref-IC	1,26..24V,50mA,-30..+85°	7(KARef)	Nec	-
µPC1A	Lin-IC	Amp.,Ucc=12V,>35dB,>1,5MHz	82	Nec,Tho	-
µPC1B	Lin-IC	=µPC1A: SMD	10-FLP	Nec,Tho	-
µPC2002(H,V)	Lin-IC	=TDA2002(H,V)	86/5Pin	Nec	TDA2002
µPC2005V	Lin-IC	=TDA2005	11-SQL	Nec	TDA2005
µPC209C,D	Lin-IC	Dual,Video-amp.,-20..+70/80°	14-DIP,DIC	NEC	(µPC4359)
µPC20C	Lin-IC	AF Pamp,20V,1A,1,5W(8Ω),-20..+75°	14-DIP+g	Nec	-
µPC2200GR	Lin-IC	=µPC2200H: SMD	8-MDIP	Nec	-
µPC2200H	Lin-IC	DC Motor-Driver,Ucc=1,8..6V	85/4Pin	Nec	-
µPC2210H	Lin-IC	DC Motor-Driver,Ucc=3,6..16V	85/5Pin	Nec	-
µPC2251H	VR-IC	System-reset,+3V,40mA,active lo	85/4Pin	Nec	-
µPC2252H	VR-IC	System-reset,+3V,40mA,active hi	85/4Pin	Nec	-
µPC2253H	VR-IC	System-reset,+5V,40mA,active lo	85/4Pin	Nec	-
µPC2254H	VR-IC	System-reset,+5V,40mA,active hi	85/4Pin	Nec	-
µPC2255H	VR-IC	System-reset,+5V,40mA,active lo	85/4Pin	Nec	-
µPC2256H	VR-IC	System-reset,+5V,40mA,active hi	85/4Pin	Nec	-
µPC2260V	VR-IC	µComp. System Reset,+5V,0,5A	86/5Pin	Nec	-
µPC2270ACX	VR-IC	µComp. System Reset,+5V,35mA	8-DIP	NEC	-
µPC2270AGR	VR-IC	µComp. System Reset,+5V,35mA	8-MDIP	Nec	-
µPC2270AHA	VR-IC	µComp. System Reset,+5V,35mA	9-SIP	Nec	-
µPC2313CA	Lin-IC	→KA8102	22-SDIP	Nec	KA8102
µPC2315CA	Lin-IC	→KA2315	30-SDIP	Nec	KA8104
µPC2317CA	Lin-IC	-		Nec	KA8103
µPC2320GS	Lin-IC	VTR,4x Head Amp.	36-SMDIP	Nec	-
µPC2326GT	Lin-IC	VTR (S-VHS),6x Head amplifier	48-SMDIP	Nec	-
µPC23C	Lin-IC	TV,Tuner AFC,Ucc=20V	14-DIP	NEC	-
µPC2405HF	VR-IC	PNP-Trans.,+5V,1A,Iso	17b	NEC	-
µPC2406HF	VR-IC	PNP-Trans.,+6V,1A,Iso	17b	NEC	-
µPC2407HF	VR-IC	PNP-Trans.,+7V,1A,Iso	17b	NEC	-
µPC2408HF	VR-IC	PNP-Trans.,+8V,1A,Iso	17b	NEC	-
µPC2409HF	VR-IC	PNP-Trans.,+9V,1A,Iso	17b	NEC	-
µPC2410HF	VR-IC	PNP-Trans.,+10V,1A,Iso	17b	NEC	-
µPC2412HF	VR-IC	PNP-Trans.,+12V,1A,Iso	17b	NEC	-
µPC2415HF	VR-IC	PNP-Trans.,+15V,1A,Iso	17b	NEC	-
µPC2418HF	VR-IC	PNP-Trans.,+18V,1A,Iso	17b	NEC	-
µPC24A05HF	VR-IC	PNP-Trans.,+5V,2A,Iso	17b	NEC	-
µPC24A12HF	VR-IC	PNP-Trans.,+12V,2A,Iso	17b	NEC	-
µPC24A15HF	VR-IC	PNP-Trans.,+15V,2A,Iso	17b	NEC	-
µPC24M05HF	VR-IC	PNP-Trans.,+5V,0,5A,Iso	17b	NEC	-
µPC24M06HF	VR-IC	PNP-Trans.,+6V,0,5A,Iso	17b	NEC	-
µPC24M07HF	VR-IC	PNP-Trans.,+7V,0,5A,Iso	17b	NEC	-

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µPC24M08HF	VR-IC	PNP-Trans., +8V, 0,5A, Iso	17b	NEC	-
µPC24M09HF	VR-IC	PNP-Trans., +9V, 0,5A, Iso	17b	NEC	-
µPC24M10HF	VR-IC	PNP-Trans., +10V, 0,5A, Iso	17b	NEC	-
µPC24M12HF	VR-IC	PNP-Trans., +12V, 0,5A, Iso	17b	NEC	-
µPC24M15HF	VR-IC	PNP-Trans., +15V, 0,5A, Iso	17b	NEC	-
µPC24M18HF	VR-IC	PNP-Trans., +18V, 0,5A, Iso	17b	NEC	-
µPC2500H,AH	Lin-IC	AF Pamp, BTL, 25V, 8A, 40W(13V/2Ω)	12-SILP	Nec	-
µPC2502V	Lin-IC	2x AF Pamp, BTL, 25V, 2x 19W(13,2V/4Ω)	15-QILP	Nec	-
µPC2505H	Lin-IC	AF Pamp, BTL, 25V, 8A, 40W(13,2V/2Ω)	12-SILP	Nec	-
µPC2506V	Lin-IC	AF Pamp, BTL, 25V, 8A, 40W(13,2V/2Ω)	15-QILP	Nec	-
µPC250A	Op-IC	MOS-FET, ±18V, -20..+80°	81	Nec	LH0022, SN72770, ж A740H
µPC251A	Op-IC	Dual, Series 747, ±18V, -20..80°	82	Nec	-
µPC251C,D	Op-IC	Dual, Series 158, ±18V, -20..+70/80u	8-DIP,DIC	Nec	-
µPC251G,G2	Op-IC	=жPC251C,D: SMD	8-MDIP	Nec	-
µPC252A	Op-IC	Lo-power, MOS-Pre, ±18V, -20..+80°	81	Nec	-
µPC2530GS	Lin-IC	AM-Tuner, for Car Radio	36-SMDIP	Nec	-
µPC2531GS	Lin-IC	FM-Pre/Mix/Osc/IF	20-MDIP	Nec	-
µPC2533GS	Lin-IC	AM-Tuner, for Car Radio	36-SMDIP	Nec	-
µPC2535GH-2A5	Lin-IC	FM-Tuner for Car Radio	48-MP	Nec	-
µPC253A	Op-IC	Lo-power, ±18V, -20..+80°	81	Nec	-
µPC253D	Op-IC	=жPC253A: Fig. →	8-DIC	Nec	-
µPC254A	Op-IC	GenP, ±22V, -20..+80°	81	Nec	-
µPC254D	Op-IC	=жPC254A: Fig. →	8-DIC	Nec	TA75254..
µPC255A	Op-IC	f. Servo-Amp.	81	Nec	-
µPC2560GS	Lin-IC	Sound Control, Ucc=8,5..13,2V	36-SMDIP	Nec	-
µPC258C,D	Op-IC	Dual, Series 158, ±18V, -20..70/80u	8-DIP,DIC	Nec	-
µPC258G,G2	Op-IC	=жPC258C,D: SMD	8-MDIP	Nec	-
µPC259C	Op-IC	Dual, Lo-noise, ±18V, -20..70°	8-DIP	Nec	(µPC4560C)
µPC259G,G2	Op-IC	=жPC259C: SMD	8-MDIP	Nec	(µPC4560G,G2)
µPC2605H	VR-IC	+5V, 0,5A, Uin=±100V (Surge)	17b	NEC	-
µPC2610H	VR-IC	+10V, 0,5A, Uin=±100V (Surge)	17b	NEC	-
µPC2708T	Lin-IC	BS, Converter, 2,9GHz, Ucc=5V	46	Nec	-
µPC2708T(TB)	Lin-IC	RF amplifier, 2,9GHz, 15dB(50Ω), Ucc=5V	SOT-363	Nec	-
µPC2709T	Lin-IC	BS, Converter, 2,3GHz, Ucc=5V	46	Nec	-
µPC2709T(TB)	Lin-IC	RF amplifier, 2,3GHz, 23dB(50Ω), Ucc=5V	SOT-363	Nec	-
µPC2709TB	Lin-IC	-	46(2mm)	Nec	→?PC2709TB
µPC2710T	Lin-IC	BS, Buffer Amp., 1GHz, Ucc=5V	46	Nec	-
µPC2710T(TB)	Lin-IC	Cell-Phone Wide Band amplifier, 1GHz, Ucc=5V	SO-6	Nec	-
µPC2711T	Lin-IC	BS, Buffer Amp., 2,9GHz, Ucc=5V	46	Nec	-
µPC2711T(TB)	Lin-IC	Wide-band amplifier, 2,9GHz, Ucc=5V	MSOP-6	Nec	-
µPC2711TB	Lin-IC	-	46(2mm)	Nec	→?PC2711TB
µPC2712T	Lin-IC	BS, Buffer Amp., 2,6GHz, Ucc=5V	46	Nec	-
µPC2712T(TB)	Lin-IC	Wide-band amplifier, 2,6GHz, Ucc=5V	MSOP-6	Nec	-
µPC2712TB	Lin-IC	-	46(2mm)	Nec	→?PC2712TB
µPC2713T	Lin-IC	BS, Buffer Amp., 1,2GHz, Ucc=5V	46	Nec	-
µPC2713T	Lin-IC	Wide-band LN amplifier, 1,2GHz, Ucc=5V	MSOP-6	Nec	-
µPC2714T	Lin-IC	GPS, Buffer Amp., 1,8GHz, Ucc=3,4V	46	Nec	-
µPC2714T	Lin-IC	Wide-band amplifier, 1,8GHz, Ucc=3.4V	MSOP-6	Nec	-
µPC2715T	Lin-IC	GPS, Buffer Amp., 1,2GHz, Ucc=3,4V	46	Nec	-
µPC2715T	Lin-IC	Wide-band amplifier, 1,2GHz, Ucc=3.4V	MSOP-6	Nec	-
µPC271C,D,ED	Comp-IC	Series 111, ±18V, -20..+70/80°	8-DIP,DIC	Nec	111..211..(µPC311C)
µPC271G,G2	Comp-IC	=жPC271C,D,ED: SMD	8-MDIP	Nec	111...211..(µPC311G)
µPC2721GR	Lin-IC	DBS, Converter, 2GHz, Ucc=5V	8-MDIP	Nec	-
µPC2721GV	Lin-IC	=жPC2721GR:	8-SSMDIP	Nec	-
µPC2722GR	Lin-IC	DBS, Converter, 2GHz, Ucc=5V	8-MDIP	Nec	-
µPC2722GV	Lin-IC	=жPC2722GR:	8-SSMDIP	Nec	-
µPC2723T	Lin-IC	BS, Amp., 1,1GHz, Ucc=5V	46	Nec	-
µPC2723T	Lin-IC	Differential AGC amplifier, 1,1GHz, Ucc=5V	MSOP-6	Nec	-
µPC2726T	Lin-IC	BS, Amp., 1,6GHz, Ucc=5V	46	Nec	-
µPC2726T	Lin-IC	Differential WB amplifier, 1,6GHz, Ucc=5V	MSOP-6	Nec	-
µPC272C,D	Comp-IC	Dual, Series 119, ±18V, -20..+70/80°	14-DIP,DIC	Nec	119..219..(µPC319C)
µPC272G,G2	Comp-IC	=жPC272C,D: SMD	14-MDIP	Nec	119...219..(µPC319G)
µPC2731GS	Lin-IC	BS, Converter, Ucc=5V	20-MDIP	Nec	-
µPC2734GR	Lin-IC	BS/CS, Converter, Ucc=5V	20-SSMDIP	Nec	-

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µPC2742CU	Lin-IC	TV,BS/CSTuner,QPSK	48-SDIP	Nec	-
µPC2742GT(-..)	Lin-IC	=µPC2742CU:SMD	48-SMDIP	Nec	-
µPC2743GS	Lin-IC	TV/VTR,VHF/UHF-Tuner,Ucc=9V	20-MDIP	Nec	-
µPC2744GS	Lin-IC	TV/VTR,VHF/UHF-Tuner,Ucc=9V	20-MDIP	Nec	-
µPC2745T	Lin-IC	UHF-amplifier,2,7GHz,Ucc=3V	46	Nec	-
µPC2745TB	Lin-IC	-	46(2mm)	Nec	→?PC2745TB
µPC2746T	Lin-IC	UHF-amplifier,900MHz,Ucc=3V	46	Nec	-
µPC2746TB	Lin-IC	-	46(2mm)	Nec	→?PC2746TB
µPC2747T	Lin-IC	UHF-amplifier,900MHz,Ucc=3V	46	Nec	-
µPC2748T	Lin-IC	UHF-amplifier,900MHz,Ucc=3V	46	Nec	-
µPC2749T	Lin-IC	UHF-amplifier,2,9GHz,Ucc=3V	46	Nec	-
µPC2753GR	Lin-IC	GPS,IFConverter,Ucc=3V	20-SSMDIP	Nec	-
µPC2756T	Lin-IC	-	46	Nec	→?PC2756T
µPC2757T	Lin-IC	1..2GHz,Converter,Ucc=3V	46	Nec	-
µPC2758T	Lin-IC	1..2GHz,Converter,Ucc=3V	46	Nec	-
µPC2762T	Lin-IC	UHF-amplifier,2,9GHz,Ucc=3V	46	Nec	-
µPC2762TB	Lin-IC	-	46(2mm)	Nec	→?PC2762TB
µPC2763T	Lin-IC	UHF-amplifier,2,4GHz,Ucc=3V	46	Nec	-
µPC2763TB	Lin-IC	-	46(2mm)	Nec	→?PC2763TB
µPC2766GR	Lin-IC	DigitalVideo,CompressionSystem	20-SSMDIP	Nec	-
µPC2766GS	Lin-IC	=µPC2766GR:	20-MDIP	Nec	-
µPC2768GR	Lin-IC	DownConverter,Ucc=3V	20-SSMDIP	Nec	-
µPC2771T	Lin-IC	UHF-amplifier,2,2GHz,Ucc=3V	46	Nec	-
µPC2771TB	Lin-IC	-	46(2mm)	Nec	→?PC2771TB
µPC2775GR	Lin-IC	TV/VTR,VHF/UHF-Tuner,Ucc=9V	20-SSMDIP	Nec	-
µPC2775GS	Lin-IC	=µPC2775GR:	20-MDIP	NEC	-
µPC2776T	Lin-IC	UHF-amplifier,2,7GHz,Ucc=3V	46	Nec	-
µPC2776TB	Lin-IC	-	46(2mm)	Nec	→?PC2776TB
µPC277C,D	Comp-IC	Dual,Series139,±18V,-20..+70/80°	8-DIP,DIC	Nec	139..239..(µPC339C)
µPC277G,G2	Comp-IC	=µPC277C,D:SMD	8-MDIP	Nec	139...239..(µPC339G)
µPC2781GR	Lin-IC	DigitalVideo,CompressionSystem	20-SSMDIP	Nec	-
µPC2782GR	Lin-IC	DownConverter,Ucc=5V	20-SSMDIP	Nec	-
µPC2791TB	Lin-IC	BSTunerIFSystem,Ucc=5V	46(2mm)	Nec	-
µPC2792TB	Lin-IC	BSTunerIFSystem,Ucc=5V	46(2mm)	Nec	-
µPC2794GS	Lin-IC	TV,VHF/UHF-Tuner,Ucc=9V	20-MDIP	Nec	-
µPC2795GV	Lin-IC	DownConverter,..2,15GHz,Ucc=5V	8-SSMDIP	Nec	-
µPC2797GR	Lin-IC	TV,VHF/UHF-Tuner,Ucc=9V	20-SSMDIP	Nec	-
µPC2798GR	Lin-IC	DigitalCATV,QAMIFConverter	20-SSMDIP	Nec	-
µPC27C	Lin-IC	AM/FM-IF	16-DIP	Nec	-
µPC3	Lin-IC	Video-amplifier,Ucc=30V,>20dB,>17MHz	81	Nec	-
µPC301AC	Op-IC	=µPC157C,D:0..+70°	8-DIP	Nec	-
µPC305C	VR-IC	=µPC141C:0..70°	8-DIP	Nec	µPC141C
µPC305G,G2	VR-IC	=µPC141C:0..70°	8-MDIP	Nec	µPC141G
µPC30C	Lin-IC	AM-Tuner/HF	16-DIP	Nec	-
µPC311C	Comp-IC	=µPC271C,D,ED:0..+70°	8-DIP	Nec	..111...211...311..x
µPC311G,G2	Comp-IC	=µPC271C,D,ED:0..+70°	8-MDIP	Nec	..111...211...311..x
µPC317H	VR-IC	+1,3..30V,1,5A	17l	Nec	-
µPC317HF	VR-IC	=µPC317H:Iso	17l	Nec	-
µPC318C	Op-IC	=µPC159C,D:0..+70°	8-DIP	Nec	µPC159
µPC319C	Comp-IC	=µPC272C,D:0..+70°	14-DIP	Nec	..119...219...319..x
µPC319G,G2	Comp-IC	=µPC272C,D:0..+70°	14-MDIP	Nec	..119...219...319..x
µPC3200GS	Lin-IC	TV,VHF/UHF-Tuner,Ucc=9V	20-MDIP	Nec	-
µPC3202GR	Lin-IC	TV/VTR,VHF/UHF-Tuner,Ucc=9V	20-SSMDIP	Nec	-
µPC324C	Op-IC	=µPC451C,D:0..+70°	14-DIP	Nec	-
µPC324G,G2	Op-IC	=µPC451C,D:0..+70°	14-MDIP	Nec	-
µPC337H	VR-IC	-1,3..30V,1,5A	17n	Nec	-
µPC339C	Comp-IC	=µPC177C,D,ED:0..+70°	14-DIP	Nec	..139...239...339..x
µPC339G,G2	Comp-IC	=µPC177C,D,ED:0..+70°	14-MDIP	Nec	..139...239...339..x
µPC33C	Lin-IC	2xAF-Amplifier,LN,Ucc=8..15V	14-DIP+h	Nec	-
µPC3403C	Op-IC	=µPC452C:0..+70°	14-DIP	Nec	-
µPC3403G,G2	Op-IC	=µPC452C:0..+70°	14-MDIP	Nec	-
µPC3410C	Lin-IC	2xRecorder-Rec/PlaybackAmp.,(Autoreverse)	16-DIP	Nec	TDA3410
µPC3423C	Lin-IC	Thy.-triggerctrl.,4,5..36V	8-DIP	NEC	-
µPC354D	Op-IC	Lo-drift,±22V,-20..+80°	8-DIP	Nec	-

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µPC356C	Op-IC	JFET, ±18V, 20V/µS, 0..+70°	8-DIP	Nec	µPC806C
µPC357C	Op-IC	JFET, ±18V, 50V/µS, 0..+70°	8-DIP	Nec	µPC807C
µPC358C	Op-IC	Dual, Series 158, ±16V, 0..+70°	8-DIP	Nec	-
µPC358G,G2	Op-IC	=»PC358C: SMD	8-MDIP	Nec	-
µPC358HA	Op-IC	=»PC358C: Fig.⊠	9-SIP	Nec	-
µPC379A	Comp-IC	Dual, Ucc=20V, -20..+80°	82	Nec	-
µPC3911C	Lin-IC	=»PC616C	8-DIP	Nec	µPC616C
µPC393C	Comp-IC	=»PC277C, D: 0..+70°	8-DIP	Nec	..193...293...393..»
µPC393G,G2	Comp-IC	=»PC277C, D: 0..+70°	8-MDIP	Nec	..193...293...393..»
µPC393HA	Comp-IC	=»PC277C, D: 0..+70°	9-SIP	Nec	..193...293...393..»
µPC398C	Lin-IC	=»PC649: 0..+70°	8-DIP	Nec	µPC649
µPC4061C	Op-IC	=»PC831C: -20..+80°	8-DIP	Nec	µPC831C
µPC4061G2	Op-IC	=»PC831C: -20..+80°	8-MDIP	Nec	µPC831G2
µPC4062C	Op-IC	=»PC832C: -20..+80°	8-DIP	Nec	µPC832C
µPC4062G2	Op-IC	=»PC832C: -20..+80°	8-MDIP	Nec	µPC832G2
µPC4064C	Op-IC	=»PC834C: -20..+80°	14-DIP	Nec	µPC834C
µPC4064G2	Op-IC	=»PC834C: -20..+80°	14-MDIP	Nec	µPC834G2
µPC4071C	Op-IC	=»PC821C: -20..+80°	8-DIP	Nec	µPC821C
µPC4071G,G2	Op-IC	=»PC821C: -20..+80°	8-MDIP	Nec	µPC821G
µPC4072C	Op-IC	=»PC822C: -20..+80°	8-DIP	Nec	µPC822C
µPC4072G,G2	Op-IC	=»PC822C: -20..+80°	8-MDIP	Nec	µPC822G
µPC4072HA	Op-IC	=»PC822C: -20..+80°	9-SIP	Nec	-
µPC4074C	Op-IC	=»PC824C: -20..+80°	14-DIP	Nec	µPC824C
µPC4074G,G2	Op-IC	=»PC824C: -20..+80°	14-MDIP	Nec	µPC824G
µPC4081C	Op-IC	=»PC801C, D: 0..+70°	8-DIP	Nec	µPC801C,D
µPC4081G,G2	Op-IC	=»PC801C, D: 0..+70°	8-MDIP	Nec	µPC801G
µPC4082C	Op-IC	=»PC803C, D: 0..+70°	8-DIP	Nec	µPC803C,D
µPC4082G,G2	Op-IC	=»PC803C, D: 0..+70°	8-MDIP	Nec	µPC803G
µPC4084C	Op-IC	=»PC804C, D: 0..+70°	14-DIP	Nec	µPC804C,D
µPC411C	Op-IC	JFET, Offset Trimming, 14V/µS	8-DIP	Nec	µPC811C
µPC411G	Op-IC	=»PC411C: SMD	8-MDIP	Nec	µPC811G
µPC412C	Op-IC	=»PC411C: Dual	8-DIP	Nec	µPC812C
µPC41C	Lin-IC	AF-Preamplifier, Pamp, 1W(6V)	14-DIP+g	Nec	-
µPC4250C	Op-IC	=»PC802C: 0..+70°	8-DIP	Nec	µPC802C
µPC4250G,G2	Op-IC	=»PC802C: 0..+70°	8-MDIP	Nec	µPC802G
µPC4359C	Lin-IC	=»PC209C, D: 0..+70°	14-DIP	Nec	µPC209
µPC451C,D	Op-IC	Quad, Series 124, 32V, -20..+70/80°	14-DIP,DIC	NEC	-
µPC451G,G2	Op-IC	=»PC451C, D: SMD	14-MDIP	Nec	-
µPC452C	Op-IC	Quad, Series 124, ±18V, -20..+70°	14-DIP	NEC	-
µPC452G,G2	Op-IC	=»PC452C: SMD	14-MDIP	Nec	-
µPC454D	Op-IC	Dual, Lo-drift, ±22V, -20..+80°	14-DIP	NEC	-
µPC4556C	Op-IC	Dual, ±18V, 5V/µS, 0..+70°	8-DIP	Nec	-
µPC4556G,G2	Op-IC	=»PC4556C: SMD	8-MDIP	Nec	-
µPC4557C	Op-IC	Dual, AF, Series 158, ±18V, 0..+70°	8-DIP	Nec	-
µPC4558C	Op-IC	=»PC258C, D: 0..+70°	8-DIP	Nec	-
µPC4558G,G2	Op-IC	=»PC258C, D: 0..+70°	8-MDIP	Nec	-
µPC4559C	Op-IC	Dual, AF, Series 158, ±18V, 0..+70°	8-DIP	Nec	-
µPC4560C	Op-IC	=»PC259C: 0..+70°	8-DIP	Nec	µPC259C
µPC4560G,G2	Op-IC	=»PC259C: 0..+70°	8-MDIP	Nec	µPC259G,G2
µPC4570C	Op-IC	Dual, Lo-noise, Series 158, ±18V, -20..+80°	8-DIP	Nec	..158..258..1458..,
µPC4570G,G2	Op-IC	=»PC4570C: SMD	8-MDIP	Nec	..158...258...1458..,
µPC4570HA	Op-IC	=»PC4570C: Fig.⊠	9-SIP	Nec	..158...258...1458..,
µPC4572C	Op-IC	Dual, Lo-noise, Series 180, ±7V, -20..+80°	8-DIP	Nec	-
µPC4572G2	Op-IC	=»PC4572D: SMD	8-MDIP	Nec	-
µPC4572HA	Op-IC	=»PC4572D: Fig.⊠	9-SIP	Nec	-
µPC4574C	Op-IC	Quad, Lo-noise, ±18V, -20..+80°	14-DIP	NEC	-
µPC4574G2	Op-IC	=»PC4574C: SMD	14-MDIP	Nec	-
µPC458C,D	Op-IC	Quad, Series 124, ±20V, -20..+70/80°	14-DIP,DIC	NEC	-
µPC458G,G2	Op-IC	=»PC458C, D: SMD	14-MDIP	Nec	-
µPC4741C	Op-IC	=»PC458C, D: 0..70°	14-DIP	Nec	-
µPC4741G,G2	Op-IC	=»PC458C, D: 0..+70°	14-MDIP	Nec	-
µPC494C	Lin-IC	Sw-Reg Ctrl., +5V, 0,25A, -20..+85°	16-DIP	Nec	IR3M02, KA7500, TL494
µPC494G,GS	Lin-IC	=»PC494C: SMD	16-MDIP	Nec	-
µPC51A	Op-IC	GenP, 24V, ..10MHz, -55..+125°	81	Nec	-

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µPC53A	Op-IC	GenP, 24V, ..10MHz, -55..+125°	82	Nec	-
µPC551G	Lin-IC	Camera Controll	10-FLP	Nec	-
µPC554	Lin-IC	FM Stereo-Decoder	14-DIP	NEC	-
µPC555(H)	Lin-IC	HF, IF, 10..150MHz	7-SIP	Nec	-
µPC558(C)	Lin-IC	-		Nec	-
µPC55A	Op-IC	GenP, Series 109, ±18V, -20..+80°	81	Nec	-
µPC55D	Op-IC	=иPC55A: Fig.☒	8-DIC	Nec	-
µPC563(H)	Lin-IC	~µPC1020	10-SIL	Nec	µPC1020
µPC566C2,H,H3	Lin-IC	AF-Preamplifier, Low Noise, Ucc=7V	7-SIP	Nec	-
µPC571C	Lin-IC	AF Pamp, 6,5W(c12V/8Ω)	14-DILP	Nec	-
µPC572C	Lin-IC	TV, VD-Osc/Dr.	14-DIP	NEC	-
µPC573C	Lin-IC	Recorder-AF-V + Equal.	16-DIP	Nec	-
µPC574(J)	VR-IC	Tuner-Stab., 31..35V, 10mA	7j	Nec	TAA550, ZTK33
µPC575C,C2	Lin-IC	AF Pamp, 20V, 1A, 2W(13V/8Ω)	8-DIP+h	Nec	-
µPC576(H)	Lin-IC	AF Pamp, 27V, 1,5A, 3,5W(18V/8Ω)	10-SIL	Nec	-
µPC577(H)	Lin-IC	FM-IF	7-SIP	Nec	-
µPC578C	Lin-IC	AF Pamp, ±15V, 2A, 7W(±12V/8Ω)	14-DILP	Nec	-
µPC580C	Lin-IC	CTV-Chroma	24-DIP	Nec	-
µPC585C	Lin-IC	FM Stereo-Decoder	14-DIP	NEC	-
µPC587C,C2	Lin-IC	FM Stereo-Decoder	14-DIP	NEC	pPC1026
µPC588G	Lin-IC	Camera, Level Detector	10-FLP	Nec	-
µPC588M	Lin-IC	=иPC588G:	Film	Nec	-
µPC589G	Lin-IC	Camera, Autom. Aperture Control	10-FLP	Nec	-
µPC590G	Lin-IC	Camera, Autom. Aperture Control	10-FLP	Nec	-
µPC592H,H2	Lin-IC	AF-Preamplifier, Equal., Ucc=8V	7-SIP	Nec	-
µPC595C	Lin-IC	TV, Video-IF, AGC, Ucc=8,5..14V	14-DIP	NEC	-
µPC596C	Lin-IC	TV, Video-IF Demodulator, Ucc=8,5..14V	8-DIP	NEC	-
µPC59D	Op-IC	For Sample & Hold A/D Converter	14-DIP	NEC	-
µPC6012C	D/A-IC	=иPC648C,D: 0..+70°	20-DIP	Nec	µPC648C,D
µPC603D	D/A-IC	6-bit, ±18V, -20..+80°	14-DIC	NEC	-
µPC610D	D/A-IC	10-bit. ±18V, -20..+80°	18-DIC	Nec	-
µPC616A	Lin-IC	Sensor Controller, -40..+125°	5	Nec	-
µPC616C	Lin-IC	=иPC616A: -25..+85°	8-DIP	Nec	µPC3911C
µPC617C	Lin-IC	=иPC1555C: -20..+70°C	8-DIP	Nec	SA555
µPC617G,G2	Lin-IC	=иPC617C: SMD	8-MDIP	Nec	SA555D
µPC624C,D	D/A-IC	8-bit, 36V, -20..+70/80°	16-DIP,DIC	Nec	-
µPC629C	Lin-IC	Stereo Peak Level Meter	28-DIP	Nec	-
µPC635C	Lin-IC	Timer, LED Driver, Ucc=6..10V	14-DIP	NEC	-
µPC646D	A/D-IC	Analog-Block for µPC647, -20..+70°	18-DIC	Nec	-
µPC647C	A/D-IC	Digital-Block for µPC646, -20..+70°	16-DIP	Nec	-
µPC648C,D	D/A-IC	12-bit, ±18V, -20..+70/80°	20-DIP,DIC	Nec	(µPC6012C)
µPC649C,D	Lin-IC	Sample & Hold, -20..+70/80°	8-DIP,DIC	Nec	(µPC398C)
µPC650D	A/D-IC	12-bit	28-DIC	Nec	-
µPC654	D/A-IC	10-bit, Video, 30Msps, ECL/TTL Level	24-DIC	Nec	-
µPC659A(GS)	A/D-IC	8-bit, Video, 20Msps, TTL Level	24-MDIP	Nec	-
µPC659G	A/D-IC	8-bit	24-MDIP	Nec	-
µPC660G	A/D-IC	6-bit, Video, 20Msps, TTL Level	16-MDIP	Nec	-
µPC661CA	A/D-IC	6-Bit, Video, 20Msps, TTL Level	24-SDIP	Nec	-
µPC661G	A/D-IC	=иPC661CA: SMD	24-MDIP	NEC	-
µPC662GH(-2A5)	D/A-IC	8-bit, 3 Ch., 35Msps, TTL Level	48-MP	Nec	-
µPC664GS	D/A-IC	8-bit, 2 Ch., 35Msps, TTL Level	36-SMDIP	Nec	-
µPC665GS	D/A-IC	8-bit, 35Msps	16-MDIP	Nec	-
µPC666GS	D/A-IC	6-bit, 3 Channel, 35Msps	36-SMDIP	Nec	-
µPC667CT	BiMOS-D/A-IC	10-bit, 60 Msps	30-SDIP	Nec	-
µPC668GS	A/D-IC	10-bit, 20 Msps	30-SSMDIP	Nec	-
µPC71A	Comp-IC	24V, 2,5MHz, CMR=98dB, -20..+80°	81	Nec	-
µPC71D	Comp-IC	=иPC71A: Fig.☒	8-DIP	Nec	-
µPC741C	Op-IC	=иPC151C,D: 0..+70°	8-DIP	Nec	-
µPC741G,G2	Op-IC	=иPC151C,D: 0..+70°	8-MDIP	Nec	-
µPC77D	MOS-IC	Memory	14-DIP	NEC	-
µPC7805..7893AHF	VR-IC	=иPC7805H..7893H: Iso, Io-drop	17b	NEC	-
µPC7805..7893HF	VR-IC	=иPC7805H..7893H: Iso	17b	NEC	..7805..(TO-220 Iso)
µPC78L05T..L15T	VR-IC	=иPC78L05J..L15J: SMD	39b	Nec	HA178LxxUA, M5278LxxM, ..78Lxx.
µPC78M05..24AHF	VR-IC	=иPC78M05H..M24H: Iso, Io-drop	17b	NEC	-

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µPC78M05..M24HF	VR-IC	=µPC78M05H..M24H:Iso	17b	NEC	78Mxx..(TO-220Iso)
µPC7905..7924AHF	VR-IC	=µPC7905H..7924H:Iso,lo-drop	17c	Nec	-
µPC7905..7924HF	VR-IC	=µPC7905H..7924H:Iso	17c	Nec	79xx..(TO-220Iso)
µPC79M05..M24HF	VR-IC	=µPC79M05H..M24H:Iso	17c	Nec	79Mxx..(TO-220Iso)
µPC8001GR	Lin-IC	Phone,2.Mixer,IF,Ucc=3V	14-SSMDIP	Nec	-
µPC8002GR	Lin-IC	Phone,2.Mixer,IF,Ucc=3V	20-SSMDIP	Nec	-
µPC801C,D	Op-IC	GenP,JFET,±18V,-20..+70/80°	8-DIP,DIC	Nec	µPC821C,µPC831C,(µPC4081C)
µPC801G,G2	Op-IC	=µPC801C,D:SMD	8-MDIP	Nec	µPC821G,µPC831G,(µPC4081G)
µPC802C	Op-IC	Lo-power,progr.,±18V,-20..+70°	8-DIP	Nec	(µPC4250C)
µPC802G,G2	Op-IC	=µPC802C:SMD	8-MDIP	Nec	(µPC4250G)
µPC803C,D	Op-IC	Dual,JFET,±18V,-20..+70/80°	8-DIP,DIC	Nec	µPC822C,µPC832C,(µPC4082C)
µPC803G,G2	Op-IC	=µPC803C:SMD	8-MDIP	Nec	µPC822G,µPC832G,(µPC4082G)
µPC804C,D	Op-IC	Quad,JFET,±18V,-20..+70/80°	14-DIP,DIC	NEC	µPC824C,µPC834C,(µPC4084C)
µPC806C	Op-IC	=µPC356C:-20..+70°	8-DIP	Nec	(µPC356C)
µPC807C	Op-IC	=µPC357C:-20..+70°	8-DIP	Nec	(µPC357C)
µPC8100GR	Lin-IC	Phone,800..900MHz Down Conv.	20-SSMDIP	Nec	-
µPC8101GR	Lin-IC	Digital Cordless Phone	20-SSMDIP	Nec	-
µPC8102T	Lin-IC	Telecom,Pager,150..330MHz Amp.	46	Nec	-
µPC8103T	Lin-IC	Telecom,Pager,150..330MHz Mixer	46	Nec	-
µPC8104GR	Lin-IC	Digital Phone,Up Converter,Ucc=3	20-SSMDIP	Nec	-
µPC8105GR	Lin-IC	Digital Phone,400MHz,Ucc=5V	16-SSMDIP	Nec	-
µPC8106T	Lin-IC	Cordless Phone,Up Conv.,Ucc=3V	46	Nec	-
µPC8108T	Lin-IC	Telecom,Pager,150..930MHz Mixer	46	Nec	-
µPC8109T	Lin-IC	Cordless Phone,Up Conv.,Ucc=3V	46	Nec	-
µPC8110GR	Lin-IC	Digital Phone,Modulator,Ucc=3V	20-SSMDIP	Nec	-
µPC8112T	Lin-IC	Cordless Phone,Down Conv.,Ucc=3V	46	Nec	-
µPC8116GR	Lin-IC	Digital Phone,IF System,Ucc=5V	20-SSMDIP	Nec	-
µPC8119T	Lin-IC	Digital Phone,AGC(down),Ucc=3V	46	Nec	-
µPC811C	Op-IC	JFET,Offset Trimming,-40..+85°	8-DIP	Nec	µPC411C,µPC813C
µPC811G,G2	Op-IC	=µPC811C:SMD	8-MDIP	Nec	µPC411G,µPC813G2
µPC8120T	Lin-IC	Digital Phone,AGC(up),Ucc=3V	46	Nec	-
µPC8125GR	Lin-IC	Digital Phone,Up Converter,Ucc=5V	20-SSMDIP	Nec	-
µPC8126GR	Lin-IC	Digital Phone,Modulator,Ucc=3V	20-SSMDIP	Nec	-
µPC8128TA(TB)	Lin-IC	Cell/Cordl-Phone Buff-Amp,Ucc=2,4..3,6V,800..1900MHz	SOP-6	Nec	-
µPC812C	Op-IC	=µPC811C:Dual	8-DIP	Nec	µPC412C,µPC814C
µPC812G2	Op-IC	=µPC812C:SMD	8-MDIP	Nec	µPC814G2
µPC813C	Op-IC	JFET,Offset Trimming,-40..+85°	8-DIP	Nec	(µPC811C)
µPC813G2	Op-IC	=µPC813C:SMD	8-MDIP	Nec	(µPC811G,G2)
µPC814C	Op-IC	=µPC813C:Dual	8-DIP	Nec	(µPC812C)
µPC814G2	Op-IC	=µPC814C:SMD	8-MDIP	Nec	(µPC812G,G2)
µPC8151TA(TB)	Lin-IC	Cell/Cordl-Phone Buff-Amp,Ucc=2,4..3,6V,800..1900MHz	SOP-6	Nec	-
µPC8152TA(TB)	Lin-IC	Cell/Cordl-Phone Buff-Amp,Ucc=2,4..3,6V,800..1900MHz	SOP-6	Nec	-
µPC815C,D	Op-IC	Lo-noise,lo-drift,±22V,-20..+70/80°	8-DIP,DIC	Nec	µPC816C,D
µPC816C,D	Op-IC	=µPC815C,D:26MHz,7,6V/µS	8-DIP,DIC	Nec	-
µPC821C	Op-IC	JFET,Lo-noise,±18V,-40..+85°	8-DIP	Nec	(µPC4071C)
µPC821G,G2	Op-IC	=µPC821C:SMD	8-MDIP	Nec	(µPC4071G2)
µPC822C	Op-IC	Dual,JFET,Lo-noise,±18V,-40..+85°	8-DIP	Nec	(µPC4072C)
µPC822G,G2	Op-IC	Dual,JFET,Lo-noise,±18V,-40..+85°	8-MDIP	Nec	(µPC4072G2)
µPC824C	Op-IC	Quad,JFET,Lo-noise,±18V,-40..+85°	14-DIP	NEC	(µPC4074C)
µPC824G,G2	Op-IC	Quad,JFET,Lo-noise,±18V,-40..+85°	14-MDIP	Nec	(µPC4074G2)
µPC831C	Op-IC	JFET,Lo-power,±18V,-40..+85°	8-DIP	Nec	(µPC4061C)
µPC831G2	Op-IC	JFET,Lo-power,±18V,-40..+85°	8-MDIP	Nec	(µPC4061G2)
µPC832C	Op-IC	Dual,JFET,Lo-power,±18V,-40..+85°	8-DIP	Nec	(µPC4062C)
µPC832G2	Op-IC	Dual,JFET,Lo-power,±18V,-40..+85°	8-MDIP	Nec	(µPC4062G2)
µPC834C	Op-IC	Quad,JFET,Lo-power,±18V,-40..+85°	14-DIP	NEC	(µPC4064C)
µPC834G2	Op-IC	Quad,JFET,Lo-power,±18V,-40..+85°	14-MDIP	Nec	(µPC4064G2)
µPC842C	Op-IC	GenP,±18V,3MHz,8,5V/µS,-40..+85°	8-DIP	Nec	-
µPC842G2	Op-IC	GenP,±18V,3MHz,8,5V/µS,-40..+85°	8-MDIP	Nec	-
µPC844C	Op-IC	Quad,GenP,±18V,3MHz,8,5V/µS,-40..+85°	14-DIP	Nec	-
µPC844G2	Op-IC	Quad,GenP,±18V,3MHz,8,5V/µS,-40..+85°	14-MDIP	Nec	-
µPC91A	Lin-IC	Analogswitch	82	Nec	-
µPC92A	Lin-IC	2xAnalogswitch	83	Nec	-
µPD1001C	MOS-µC-IC	CPU for 10 Digit Memory Calculator	28-DIP	Nec	-
µPD1010C	MOS-IC	10-Digit Printing & Display Calculator	42-DIP	Nec	-

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µPD1201C	MOS-IC	12 Digit Printing & Display Calculator	42-DIP	Nec	-
µPD1220C	MOS-µC-IC	CPU for 12 Digit 3 Memory Calculator	DIP	Nec	-
µPD1221C	MOS-µC-IC	CPU for 12 Digit Memory Calculator	42-DIP	Nec	-
µPD16300	BiCMOS-IC	41-bit DC PDP Driver	64-MP	Nec	-
µPD16301	CMOS-IC	64-bit DC PDP Driver	80-MP	Nec	-
µPD16302	CMOS-IC	40-bit EL Panel Driver	80-MP	Nec	-
µPD16304	CMOS-IC	40-bit EL Panel Driver	64-MP	Nec	-
µPD16305	CMOS-IC	40-bit AC PDP Driver	64-MP	Nec	-
µPD16306GF-	CMOS-IC	64-bit PDP, EL, FIP Driver	100-MP	Nec	-
µPD16307GF-	BiCMOS-IC	41-bit DC PDP Driver	80-MP	Nec	-
µPD16309GF-	CMOS-IC	64-bit DC PDP Driver	100-MP	Nec	-
µPD16310GF-	CMOS-IC	40-bit PDP, EL, FIP Driver	64-MP	Nec	-
µPD16311GC	MOS-IC	LED Controller/Driver	52-MP	Nec	-
µPD16312GB	MOS-IC	LED Controller/Driver	44-MP	Nec	-
µPD16320AGF-	MOS-IC	48-bit Parallel-Out Driver	80-MP	Nec	-
µPD16322GC-	CMOS-IC	32-bit Shift Register/Driver	52-MP	Nec	-
µPD16405N-	MOS-IC	TV, 160 Output TFT-LCD Source Driver	-	Nec	-
µPD16406N-	MOS-IC	TV, 120 Output TFT-LCD Source Driver	-	Nec	-
µPD16407N-	MOS-IC	TV, 160 Output TFT-LCD Source Driver	-	Nec	-
µPD16408N-	MOS-IC	TV, 192 Output TFT-LCD Color Driver	-	Nec	-
µPD16422N-	MOS-IC	120 Output TFT-LCD Gate Driver	-	Nec	-
µPD16425N-	MOS-IC	192 Output TFT-LCD Source Driver	-	Nec	-
µPD16427N-	MOS-IC	80 Output TFT-LCD Source Driver	-	Nec	-
µPD16429N-	MOS-IC	192 Output TFT-LCD Source Driver	-	Nec	-
µPD16430AGF	CMOS-IC	LCD µController/Driver	80-MP	Nec	-
µPD16431AGC	CMOS-IC	LCD µController/Driver	80-MP	Nec	-
µPD16442N-	MOS-IC	120 Output TFT-LCD Gate Driver	-	Nec	-
µPD16443BN-	MOS-IC	192 Output TFT-LCD Source Driver	-	Nec	-
µPD16444N-	MOS-IC	192 Output TFT-LCD Source Driver	-	Nec	-
µPD16445N-	MOS-IC	192 Output TFT-LCD Source Driver	-	Nec	-
µPD16447N-	MOS-IC	TV, 120 Output TFT-LCD Source Driver	-	Nec	-
µPD16804GS	MOS-IC	4x MOS-FET-Dr (H Bridge Driver)	16-MDIP	Nec	-
µPD16805GS	MOS-IC	4x MOS-FET-Dr (H Bridge Driver)	16-MDIP	Nec	-
µPD16823GS	MOS-IC	6x MOS-FET-Dr (H Bridge), 0,5A	20-MDIP	Nec	-
µPD1701C-	CMOS-IC	PLL-Frequency-Synth. + ARI + Clock	28-DIP	Nec	-
µPD1703C-	CMOS-IC	PLL-Frequency-Synth. + Memory	28-DIP	Nec	-
µPD1704C-	CMOS-IC	PLL-Frequency-Synth. + Memory + clock	42-DIP	Nec	-
µPD1705C-	CMOS-IC	PLL-Frequency-Synth.	42-DIP	Nec	-
µPD1706C-	CMOS-IC	PLL-Frequency-Synth. + LCD-Dec. + clock	64-FLP	Nec	-
µPD1707G-	CMOS-IC	PLL-Frequency-Synth.	S2-FLP	Nec	-
µPD1708G-	CMOS-IC	PLL-Frequency-Synth. + LCD-Dec. + clock	S2-FLP	Nec	-
µPD1710G-	CMOS-IC	PLL-Frequency-Synth. + ARI + clock	S2-FLP	Nec	-
µPD1801C	MOS-µC-IC	CPU for 8 Digit Calculator	28-DIP	Nec	-
µPD1802C	MOS-µC-IC	CPU for 8 Digit Total Memory Calculator	28-DIP	Nec	-
µPD1803C	MOS-µC-IC	CPU for 8 Digit 1 Memory Calculator	28-DIP	Nec	-
µPD1851G	MOS-µC-IC	CPU for 8 Digit Calculator	FLP	Nec	-
µPD1913C	CMOS-IC	IR-Remote Control Transmitter, 736 Codes	16-DIP	Nec	KS5803A
µPD1937C	MOS-IC	IR-Remote Control Receiver (20channel)	16-DIP	Nec	-
µPD1943G	CMOS-IC	IR-Remote Control Transmitter, 8960 Codes	20-MDIP	Nec	KS5803B
µPD1963C	CMOS-IC	Clock, Stepping Motor, Alarm Tone	-	Nec	-
µPD1986C	MOS-IC	IR-Remote Control Transmitter (27 channel)	16-DIP	Nec	-
µPD1987C	MOS-IC	IR-Remote Control Receiver (20channel)	16-DIP	Nec	-
µPD1990AC	CMOS-IC	Digital µComp. Time Counter	-	Nec	-
µPD1993G	CMOS-IC	Digital Clock, 6 Digit, Alarm, LCD	-	Nec	-
µPD2006G	CMOS-IC	Digital Clock, 3,5 Digit, Alarm, LED	-	Nec	-
µPD2101ALC(-2,-4)	NMOS-sRAM-IC	256x4-bit, <450..250nS, -10..+70°	22-DIP	Nec	2101..
µPD2102ALC(-2,-4)	NMOS-sRAM-IC	1024x1 Bit, <450..250nS, -10..+70°	16-DIP	Nec	2102..
µPD2111ALC(-2,-4)	NMOS-sRAM-IC	256x4-bit, <450..250nS, -10..+70°	18-DIP	Nec	2111..
µPD2114..-0..-5	NMOS-sRAM-IC..	1024x4-bit, <450nS, 0..+70°	18-DIP,DIC	Nec	2114..
µPD2115	MOS-sRAM-IC....	1024x1 Bit, <95nS	16-	Nec	2115..
µPD2125	MOS-sRAM-IC....	1024x1 Bit, <95nS	16-	Nec	2125..
µPD2147..-2..-5	NMOS-sRAM-IC..	4096x1 Bit, <70nS, 0..+70°	18-DIP,DIC	Nec	2147..
µPD2149..-0..-2	NMOS-sRAM-IC..	1024x4-bit, <55nS, 0..+70°	18-DIP,DIC	Nec	2148..
µPD2167D-2..-3	NMOS-sRAM-IC	16384x1 Bit, <70nS, 0..+70°	20-DIP,DIC	Nec	2167..

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µPD22100C	CMOS-IC	4x4 Crosspoint Switch, -40..+85°	16-DIP	Nec	-
µPD22100GS	CMOS-IC	=µPD22100C: SMD	16-MDIP	NEC	-
µPD22148CA	CMOS-IC	4x8 Crosspoint Switch, -40..+85°	22-SDIP	Nec	-
µPD2308C,D	NMOS-ROM-IC	Mask. progr., 8192 Bit, -10..+70°	24-DIP,DIC	Nec	i2308, i8308
µPD23128D	NMOS-ROM-IC	Mask. progr., 16kBx8-bit, 0..+70°	24-DIC	Nec	-
µPD2316(A,B)C,D	NMOS-ROM-IC	Mask. progr., 4096x8-bit	24-DIP,DIC	Nec	-
µPD2316AC,AD	NMOS-ROM-IC	Mask. progr., 16384-bit, -10..+70°	24-DIP,DIC	Nec	I2316A, i8316A
µPD2364C,D	NMOS-ROM-IC	Mask. progr., 8192x8-bit, 0..+70°	24-DIP,DIC	Nec	-
µPD261C	MOS-IC	7..8 Segment Display Decoder	20-DIP	Nec	-
µPD262C	MOS-IC	Counter	-	Nec	-
µPD264C	MOS-IC	-			Nec-
µPD2716D,D-2	EPROM-IC	NMOS, 2048x8-bit, 5V, <450..390nS	24-DIP	Nec	2716..
µPD2732D,D-4	EPROM-IC	NMOS, 4096x8-bit, 5V, <450..390nS	24-DIP	Nec	2732..
µPD274C	MOS-IC	CPU for 8 Digit Calculator	28-DIP	Nec	-
µPD275C	MOS-IC	CPU for 8 Digit Calculator	28-DIP	Nec	-
µPD277C	MOS-IC	CPU for 8 Digit Calculator	28-DIP	Nec	-
µPD2801C	CMOS-IC	CB-Band Channel selector	28-DIP	Nec	-
µPD2810C	CMOS-IC	CB-Band, PLL Freq. Synthesizer	24-DIP	Nec	-
µPD2812C	CMOS-IC	CB-Band, PLL Freq. Synthesizer	22-DIP	Nec	-
µPD281C	MOS-IC	CPU for 12 Digit Memory Calculator	24-DIP	Nec	-
µPD282C	MOS-IC	CPU for 12 Digit Memory Calculator	24-DIP	Nec	-
µPD2835CS	Lin-IC	PLL-Synthesizer, Prescaler, 920MHz	18-DIP	Nec	-
µPD2835GS	Lin-IC	=µPD2835CS: SMD	18-MDIP	Nec	-
µPD2836CS	Lin-IC	PLL-Synthesizer, Prescaler, 920MHz	18-DIP	Nec	-
µPD2836GS	Lin-IC	=µPD2836CS: SMD	20-MDIP	Nec	-
µPD2845GR	MOS-IC	Phone, Pager, PLL Synthesizer	16-SSMDIP	Nec	-
µPD284C	MOS-IC	CPU for 12 Digit Memory Calculator	42-DIP	Nec	-
µPD299C	MOS-IC	CPU for 12 Digit Calculator, FLT	42-DIP	Nec	-
µPD3140GS	BiCMOS-IC	Cordless Phone, 2xPLL Synthesizer	20-SSMDIP	Nec	-
µPD3150GS	BiCMOS-IC	Analog Phone, 2xPLL Synthesizer	20-SSMDIP	Nec	-
µPD3160GS	BiCMOS-IC	Digital Phone, PLL Synthesizer	20-SSMDIP	Nec	-
µPD317C	MOS-IC	CPU for Rate Calculation Scale	28-DIP	Nec	-
µPD3301-2C,D	NMOS-I/O-IC	CRT Controller, 5V, 3MHz, 0..+70°	40-DIP,DIC	Nec	-
µPD369C,D	MOS-I/O-IC	UART for µComp., 0..+70°	42-DIP,DIC	Nec	-
µPD371C,D	NMOS-I/O-IC	MC (Cassette Tape) Controller for µComp	42-DIP,DIC	Nec	-
µPD372C,D	NMOS-I/O-IC	FDD Controller for µComp	42-DIP,DIC	Nec	-
µPD379C,D	NMOS-I/O-IC	USART for µComp., 0..+70°	42-DIP,DIC	Nec	-
µPD4016-1..-3	NMOS-sRAM-IC	2048x8-bit, <250..150nS	24-DIP	Nec	4016..
µPD402D	NMOS-sRAM-IC	256x1 Bit, <450nS, -10..+75°	18-DIC	Nec	-
µPD404D	NMOS-dRAM-IC	1024x1 Bit, <450nS, 0..+70°	18-DIC	Nec	-
µPD405D(-1,-2)	NMOS-sRAM-IC	1024x1 Bit, <95..80nS, 0..+70°	18-DIC	Nec	-
µPD408	dRAM-IC	4096x1 Bit, <300nS	22-	Nec	-
µPD409	dRAM-IC	4096x1 Bit, <190nS	22-	Nec	-
µPD4104-0..-2	NMOS-sRAM-IC	4096x1 Bit, <300..200nS	18-DIP	Nec	-
µPD410D(-1,-2)	NMOS-sRAM-IC	4096x1 Bit, <200..100nS, 0..+70°	22-DIC	Nec	IM7410F-..
µPD41101C(-..)	NMOS-RAM-IC	Video, NTSC line buffer, 910x8Bit	24-DIP	Nec	-
µPD41101G(-..)	NMOS-RAM-IC	=µPD41101C: SMD	24-MDIP	NEC	-
µPD41102C(-..)	NMOS-RAM-IC	Video, PAL line buffer, 1135x8Bit	24-DIP	Nec	-
µPD41102G(-..)	NMOS-RAM-IC	=µPD41102C: SMD	24-MDIP	NEC	-
µPD411D(-1,-2,-3)	NMOS-dRAM-IC	4096x1 Bit, <350..150nS, 0..+70°	22-DIC	Nec	MM5280..MN1001..N2680..,
µPD41264C-	NMOS-VRAM-IC	64kBx4-bit, video RAM	24-DIP	Nec	-
µPD412C,D	NMOS-sRAM-IC	256x4-bit, <430nS, -10..+70°	24-DIP,DIC	Nec	-
µPD414D(-E,-1)	NMOS-dRAM-IC	4096x1 Bit, <350..250nS, 0..+70°	16-DIC	Nec	2660..4027..
µPD4164C,D-..	NMOS-dRAM-IC	65536x1 Bit, <250..150nS, 0..+70°	16-DIP,DIC	Nec	4164..
µPD416C,D-..	NMOS-dRAM-IC	16384x1 Bit, <300..120nS, 0..+75°	16-DIP,DIC	Nec	4116..
µPD42101C(-..)	CMOS-RAM-IC	Video, NTSC line buffer, 910x8Bit	24-DIP	Nec	-
µPD42101G(-..)	CMOS-RAM-IC	=µPD42101C: SMD	24-MDIP	NEC	-
µPD42102C(-..)	CMOS-RAM-IC	Video, PAL line buffer, 1135x8Bit	24-DIP	Nec	-
µPD42102G(-..)	CMOS-RAM-IC	=µPD42102C: SMD	24-MDIP	NEC	-
µPD42264C-	MOS-VRAM-IC	64kBx4-bit, video RAM, <100nS	24-DIP	Nec	-
µPD42270-60	RAM-IC	Video, Frame Memory, 239330x4Bit	28-DIP	Nec	-
µPD42271GF(-3BR)..	MOS-IC	CTV, PAL/NTSC PIP Generator	64-MP	Nec	-
µPD42272AGF(-3BR)	MOS-IC	CTV, PAL/NTSC PIP Generator	64-MP	Nec	-
µPD42273V-	VRAM-IC	256kBx4 Bit, -10: <100nS, -12: <120nS	28-MDIP	Nec	-

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µPD42274V-	VRAM-IC	256kBx4Bit,-10:<100nS,-12:<120nS,-80:<80nS	28-MDIP	Nec	-
µPD42275LE-..	VRAM-IC	128kBx8Bit,-10:<100nS,-12:<120nS,-80:<80nS	40-MDIP	Nec	-
µPD42280GU(-..)..	CMOS-IC	=µPD42280V:SMD	28-MDIP	Nec	-
µPD42280V(-..)....	CMOS-IC	CTV,2MB Field Buffer	28-SQP	Nec	-
µPD443D	CMOS-sRAM-IC..	1024x1Bit,<200nS	16-DIC	Nec	6508
µPD444C-0..-3	CMOS-sRAM-IC..	1024x4-bit,<450..200nS	18-DIP	Nec	2114..
µPD446C,D-0..-2	CMOS-sRAM-IC....	2048x8-bit,<200..120ns	24-DIP	Nec	6116..
µPD447C,D-0..-2	CMOS-sRAM-IC....	2048x8-bit,<200..120ns	24-DIP	Nec	-
µPD451D	EEPROM-IC	32x8-bit	24-DIC	Nec	-
µPD454D	EEPROM-IC	NMOS,256x8-bit,<800nS,-10..+70°	24-DIC	Nec	-
µPD458D	EEPROM-IC	NMOS,1024x8-bit,<450nS,-10..+70°	28-DIC	Nec	-
µPD463D	NMOS-ROM-IC...	Mask.progr.,2048-bit,-10..+70°	24-DIC	Nec	-
µPD464C,D	MOS-ROM-IC	Mask.progr.,2048-bit,-10..+70°	24-DIP,DIC	Nec	-
µPD465C,D	NMOS-ROM-IC...	Mask.progr.,8192Bit,-10..+70°	24-DIP,DIC	Nec	-
µPD466C,D	NMOS-ROM-IC...	Mask.progr.,16384-bit,-10..+70°	28-DIP,DIC	Nec	-
µPD4701AC	CMOS-IC	Incremental Encoder,Counter	24-DIP	Nec	-
µPD4701AGT	CMOS-IC	=µPD4701AC:SMD	24-MDIP	NEC	-
µPD4702C	CMOS-IC	Incremental Encoder,Up-Down Counter	20-DIP	Nec	-
µPD4702G	CMOS-IC	=µPD4702C:SMD	20-MDIP	NEC	-
µPD4703C	CMOS-IC	Incremental Encoder,Up-Down Counter	20-DIP	Nec	-
µPD4703G	CMOS-IC	=µPD4703C:SMD	20-MDIP	NEC	-
µPD4704C	CMOS-IC	8-bit Up-Down Counter	20-DIP	Nec	-
µPD4704G	CMOS-IC	=µPD4704C:SMD	20-MDIP	NEC	-
µPD4705C	CMOS-IC	8-bit Up-Down Counter	20-DIP	Nec	-
µPD4705G	CMOS-IC	=µPD4705C:SMD	20-MDIP	NEC	-
µPD471D	NMOS-ROM-IC...	Character gen.,512x10-bit,0..+70°	28-DIC	Nec	-
µPD4721GS-GJG...	CMOS-IC	RS-232 Line Driver/Receiver,3,3/5V	20-SSMDIP	Nec	-
µPD4722GS-GJG...	CMOS-IC	RS-232 Line Driver/Receiver,3,3/5V	30-SSMDIP	Nec	-
µPD4723GS-GJG...	CMOS-IC	RS-232 Line Driver/Receiver,3,3/5V	30-SSMDIP	Nec	-
µPD4724GS-GJG...	CMOS-IC	RS-232 Line Driver/Receiver,3,3/5V	30-SSMDIP	Nec	-
µPD472D	NMOS-ROM-IC...	Character gen.,1024x5 Bit,0..+70°	28-DIC	Nec	-
µPD473D(-01,-02)....	NMOS-ROM-IC....	Character gen.,64x9x7 Bit,0..+70°	28-DIC	Nec	-
µPD474D(-01,-02)....	NMOS-ROM-IC....	Character gen.,64x7x9 Bit,0..+70°	28-DIC	Nec	-
µPD4990AC	CMOS-IC	Parallel I/O Calendar	14-DIP	NEC	-
µPD4990AG	CMOS-IC	=µPD4990AC:SMD	16-MDIP	NEC	-
µPD4991ACX	CMOS-IC	4-bit Parallel I/O Calendar	18-DIP	Nec	-
µPD4991AGS	CMOS-IC	=µPD4991ACX:SMD	20-MDIP	NEC	-
µPD4992CX	CMOS-IC	8-bit Parallel I/O Calendar	20-DIP	Nec	-
µPD4992GS	CMOS-IC	=µPD4992CX:SMD	20-MDIP	NEC	-
µPD501D	PMOS-ROM-IC...	1024(128x8)bit,-10..+70°	24-DIC	Nec	-
µPD502D	PMOS-ROM-IC...	2048(256x8)Bit,-10..+70°	24-DIC	Nec	-
µPD503D	PMOS-ROM-IC...	4096(512x8)Bit,-10..+70°	24-DIC	Nec	-
µPD5101C-E	CMOS-sRAM-IC..	256x4-bit,<800nS,0..+70°	22-DIP	Nec	..5101..2101..
µPD5101LC(-1)	CMOS-sRAM-IC..	256x4-bit,<650nS	22-DIP	Nec	5101L..2101L..
µPD5200C,D	CMOS-IC	Dual,Analog Sw,±22V,-20..+70/80°	14-DIP	NEC	-
µPD5200G	CMOS-IC	=µPD5200C:SMD	14-MDIP	Nec	-
µPD5201C,D	CMOS-IC	Quad,Analog Sw,±22V,-20..+70/80°	16-DIP	Nec	-
µPD5201G	CMOS-IC	=µPD5201C:SMD	16-MDIP	Nec	-
µPD5205CA	CMOS-IC	µComp.Interface,±22V,-20..+85°	24-SDIP	Nec	-
µPD5205G	CMOS-IC	=µPD5205C:SMD	24-MDIP	Nec	-
µPD541C	PMOS-µC-IC	4-bit,ROM,RAM,-10..+70°	42-DIP	Nec	-
µPD542C	PMOS-µC-IC	4-bit,ROM,RAM,-10..+70°	42-DIP	Nec	-
µPD543C	PMOS-IC	2kx8-bit ROM,progr.I/O Port	42-DIP	Nec	-
µPD546C	PMOS-µC-IC	4-bit,ROM,RAM,I/O Port	42-DIP	Nec	-
µPD547C	PMOS-µC-IC	4-bit,RAM,ROM,I/O Port	42-DIP	Nec	-
µPD548C	PMOS-µC-IC	4-bit,ROM,RAM,I/O Port	42-DIP	Nec	-
µPD549C	PMOS-IC	Programmable 8 Segment Display µController	28-DIP	Nec	-
µPD550C	PMOS-µC-IC	4-bit,RAM,ROM,I/O Port	42-DIP	Nec	-
µPD5555C	CMOS-IC	Timer,18V,-20..+70°	8-DIP	NEC	-
µPD5555G	CMOS-IC	=µPD5555C:SMD	8-MDIP	Nec	-
µPD5556C	CMOS-IC	Dual,Timer,18V,-20..+70°	14-DIP	NEC	-
µPD5556G	CMOS-IC	=µPD5556C:SMD	14-MDIP	Nec	-
µPD555D	PMOS-IC	µCOM-42 Hardware Simulator	64-DIC	Nec	-
µPD556D	PMOS-IC	µCOM-43/44/45 Hardware Simulator	64-DIC	Nec	-

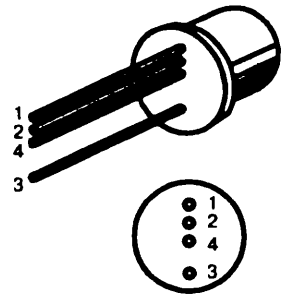
ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
µPD60001GJ(-5BG)	MOS-IC	CTV, Ghost Reduce, Filter Control	94-MP	Nec	-
µPD60002GJ(-5BG)	MOS-IC	CTV, Ghost Reduce, Filter Control	94-MP	Nec	-
µPD6140C(-001)	CMOS-IC	OSD, 2x6 Characters (5x7 Dot)	16-DIP	Nec	-
µPD6140G(-101)	CMOS-IC	=µPD6140C: SMD	16-MDIP	NEC	-
µPD6141C(-001)	CMOS-IC	OSD, 2x12 Characters (5x7 Dot)	16-DIP	Nec	-
µPD6141G(-101)	CMOS-IC	=µPD6141C: SMD	16-MDIP	NEC	-
µPD6142C(-001)	CMOS-IC	OSD, 12x24 Characters (5x7 Dot)	16-DIP	Nec	-
µPD6142G(-101)	CMOS-IC	=µPD6142C: SMD	16-MDIP	NEC	-
µPD6143C(-001)	CMOS-IC	OSD, 2x16 Characters (6x9 Dot)	16-DIP	Nec	-
µPD6143G(-101)	CMOS-IC	=µPD6143C: SMD	16-MDIP	NEC	-
µPD6144AC(-001)	CMOS-IC	OSD, 6x16 Characters (6x9 Dot)	16-DIP	Nec	-
µPD6144AG(-101)	CMOS-IC	=µPD6144AC: SMD	16-MDIP	NEC	-
µPD6145C(-001)	CMOS-IC	OSD, 12x24 Characters (6x9 Dot)	18-DIP	Nec	-
µPD6145G(-101)	CMOS-IC	=µPD6145C: SMD	20-MDIP	NEC	-
µPD6300C	CMOS-IC	20-bit ser. Shift Register/Driver	28-DIP	Nec	-
µPD63100GS	CMOS-A/D-IC	16-bit, Digital Audio	20-MDIP	Nec	-
µPD63101GC-3BH	CMOS-A/D-IC	16-bit, Digital Audio	44-MP	Nec	-
µPD63200CS	CMOS-D/A-IC	18-bit, 2 Channel, Digital Audio	20-SDIP	Nec	-
µPD63200GS	CMOS-D/A-IC	=µPD63200: SMD	16-MDIP	Nec	-
µPD6320G	CMOS-IC	FIP/LCD Static Driver, 32-bit Shift R.	52-MP	Nec	-
µPD63210GT	CMOS-D/A-IC	16-Bit, Digital Audio, Filter, Ucc=4,5..5,5V	28-MDIP	Nec	-
µPD63210LGT	CMOS-D/A-IC	16-Bit, Digital Audio, Filter, Ucc=3..5,5V	-	NEC	-
µPD6321G	CMOS-IC	FIP/LCD Static Driver, 32-bit Shift R.	52-MP	Nec	-
µPD6322C	BiMOS-IC	LED Dot (24) Driver, 4x6 Matrix	20-DIP	Nec	-
µPD6323(A,B)C	CMOS-IC	21-bit ser. Shift Register/Driver	28-DIP	Nec	-
µPD6325C	CMOS-D/A-IC	6-Bit, 4 Channel, +5V, -40..+85°	16-DIP	Nec	-
µPD6325G	CMOS-D/A-IC	6-Bit, 4 Channel, +5V, -40..+85°	16-MDIP	Nec	-
µPD6326C	CMOS-D/A-IC	6-Bit, 8 Channel, +5V, -40..+85°	16-DIP	Nec	-
µPD6332C	CMOS-IC	20-bit ser. Shift Register/Driver	28-DIP	Nec	-
µPD6335C	CMOS-D/A-IC	6-Bit, 4 Channel, +5V, -40..+85°	16-DIP	Nec	-
µPD6335G	CMOS-D/A-IC	6-Bit, 4 Channel, +5V, -40..+85°	16-MDIP	Nec	-
µPD6336C	CMOS-D/A-IC	6-Bit, 8 Channel, +5V, -40..+85°	16-DIP	Nec	-
µPD6337G	CMOS-IC	32-bit Shift Register/AC-PDP Driver	52-MP	Nec	-
µPD6340G	BiCMOS-IC	20-bit ser. Shift Register/Driver	52-MP	Nec	-
µPD6345C	BiCMOS-IC	8-bit Serial-In Parallel-Out Driver	16-DIP	Nec	-
µPD6345GS	BiCMOS-IC	8-bit Serial-In Parallel-Out Driver	16-MDIP	Nec	-
µPD6355G	CMOS-D/A-IC	16-bit, Digital Audio	28-MDIP	Nec	-
µPD6376CX	CMOS-D/A-IC	16-Bit, 2 Channel, Digital Audio	16-DIP	Nec	-
µPD6376GS	CMOS-D/A-IC	16-Bit, 2 Channel, Digital Audio	16-MDIP	Nec	-
µPD6379GR,AGR	MOS-D/A-IC	AF, 16-Bit, 2 Channel, Ucc=5V	8-MDIP	Nec	-
µPD6379LGR,ALGR	MOS-D/A-IC	AF, 16-Bit, 2 Channel, Ucc=3,3V	8-MDIP	Nec	-
µPD6380GC-3BH	CMOS-IC	Digital Audio, Signal Processor	52-MP	Nec	-
µPD6381GC-3BH	CMOS-IC	Digital Audio, Signal Processor	80-MP	Nec	-
µPD6382GF-3B9	CMOS-IC	Digital Audio, Signal Processor	80-MP	Nec	-
µPD6383GF-3BA	CMOS-IC	Digital Audio, Signal Processor	100-MP	Nec	-
µPD6397GC(-3BE)	MOS-IC	TV, BS/CS Tuner, PCM, NEC-Bus	64-MP	Nec	-
µPD6397YGC(-3BE)	MOS-IC	=µPD6397: I3C-bus	64-MP	Nec	-
µPD6400	MOS-IC	Digital VTR, Noise Red. Proc. (NTSC)	80-MP	Nec	-
µPD6401	MOS-IC	Digital VTR, Noise Red. Proc. (PAL)	80-MP	Nec	-
µPD6403A(GF-3B9)	MOS-Digi-IC	TV, PIP Controller, 256kB RAM	80-MP	Nec	-
µPD6430GF(-3B9)	MOS-IC	CTV, Delay Line, Digital Filter (16Tap)	80-MP	Nec	-
µPD6431GF(-3B9)	MOS-IC	CTV, Delay Line, Digital Filter (32Tap)	80-MP	Nec	-
µPD6450CX(-002)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	18-DIP	Nec	-
µPD6450GT(-102)	CMOS-IC	=µPD6450CX: SMD	20-MDIP	NEC	-
µPD6451ACX(-001)	CMOS-ROM-IC	OSD, 12x24 Characters (12x18 Dot)	18-DIP	Nec	-
µPD6451AGT(-...)	CMOS-IC	=µPD6451ACX: SMD	20-MDIP	NEC	-
µPD6452CS(-002)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	18-SDIP	Nec	-
µPD6452GT(-102)	CMOS-IC	=µPD6452CS: SMD	24-MDIP	NEC	-
µPD6453CY(-001)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	20-DIP	Nec	-
µPD6453GT(-101)	CMOS-IC	=µPD6453CY: SMD	20-MDIP	NEC	-
µPD6454CS(-...)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	24-SDIP	Nec	-
µPD6454GT(-...)	CMOS-IC	=µPD6454CS: SMD	24-MDIP	NEC	-
µPD6456GS,GT(-...)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	16-MDIP	Nec	-
µPD6458CS(-...)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	24-SDIP	Nec	-

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
µPD6458GT(-..)	CMOS-IC	=µPD6458CS: SMD	24-MDIP	NEC	-
µPD6460GT(-101)	CMOS-IC	OSD, 6x16 Characters (6x9 Dot)	20-MDIP	Nec	-
µPD6461GS(-..)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	20-SMDIP	Nec	-
µPD6461GT(-..)	CMOS-IC	=µPD6461GS:	24-MDIP	NEC	-
µPD6462GS(-..)	CMOS-IC	OSD, 12x24 Characters (12x18 Dot)	20-SMDIP	Nec	-
µPD6480GF(-3BA)	MOS-IC	CTV, Digital (EDTV) Color/Y-Signal	100-MP	Nec	-
µPD6485GF(-3BA)	MOS-IC	CTV, Digital Color/Y-Signal	100-MP	Nec	-
µPD6486GF(-3BA)	MOS-IC	CTV, Digital Color/Y-Signal, I^2C-bus	100-MP	Nec	-
µPD650C	CMOS-µC-IC	4-bit, 2kx8Bit ROM, 96x4Bit RAM	42-DIP	Nec	-
µPD651C	CMOS-µC-IC	4-bit, 1kx8Bit ROM, 64x4Bit RAM	42-DIP	Nec	-
µPD652C	CMOS-µC-IC	4-bit, 1kx8Bit ROM, 32x4Bit RAM	28-DIP	Nec	-
µPD6700GH-..	CMOS-IC	Static LED/FIP Driver	56-MP	Nec	-
µPD6900C	CMOS-D/A-IC	8-bit, Video, 20Msps, TTL Level	22-DIP	Nec	-
µPD6901C	CMOS-D/A-IC	6-Bit, Video, 20 Msps, TTL Level	16-DIP	Nec	-
µPD6902C	CMOS-D/A-IC	8-bit, Video, 50Msps, CMOS/TTL Level	22-DIP	Nec	-
µPD6951C	CMOS-A/D-IC	6-Bit, Video, 20 Msps, TTL Level	18-DIP	Nec	-
µPD7001C	CMOS-A/D-IC	8-bit, 4 Channel MPX, 0..+70°	16-DIP	Nec	-
µPD7002C	CMOS-A/D-IC	10-bit, 4 Channel MPX, -20..+70°	28-DIP	Nec	-
µPD7003C	CMOS-A/D-IC	8-bit, +5V, 0..+70°	24-DIP	Nec	-
µPD7003D	CMOS-A/D-IC	=µPD7003C: -20..+80°	24-DIC	Nec	-
µPD7004C	CMOS-A/D-IC	10-bit, 8 Channel MPX, -40..+85°	28-DIP	Nec	-
µPD7011C	NMOS-D/A-IC	8-bit, +5V, -20..+70°	18-DIP	Nec	-
µPD714D	PMOS-I/O-IC	MC (Cassette Tape) Interface for µComp.	24-DIC	Nec	-
µPD717D	PMOS-µC-IC	Arithm. Logic System (ALOSY), CPU	24-DIC	Nec	-
µPD718D	PMOS-µC-IC	Arithm. Logic System (ALOSY), Shift Register	24-DIC	Nec	-
µPD719D	PMOS-µC-IC	Arithm. Logic System (ALOSY), ROM	28-DIC	Nec	-
µPD7201C	NMOS-IC	8-bit Multi-Protocol Serial Controller	40-DIP	Nec	-
µPD7210C	NMOS-IC	8-bit IEEE µController, 5V, 8MHz	40-DIP	Nec	-
µPD7220C	NMOS-IC	8-bit Graphic Display µController, 5V	40-DIP	Nec	-
µPD7225G,GB	CMOS-IC	Programmable LCD Controller/Driver	52/56-MP	Nec	-
µPD7227G-..	CMOS-IC	Programmable LCD Controller/Driver	64-MP	Nec	-
µPD7228G,GA	CMOS-IC	Programmable LCD Controller/Driver	80-MP	Nec	-
µPD7229G,GA	CMOS-IC	Programmable LCD Controller/Driver	80-MP	Nec	-
µPD73128G	CMOS-ROM-IC	Mask. progr., 16kBx8-bit, 0..+70°	52-MP	Nec	-
µPD734A	PMOS-IC	Analog Switch, Ron=300Ω, Roff=1000MΩ	81	Nec	-
µPD7500G	CMOS-µC-IC	4-bit, Evaluation Chip, 256x4Bit RAM	64-	Nec	-
µPD7501G	CMOS-µC-IC	4-bit, 1024x8Bit ROM, 96x4Bit RAM	64-MP	Nec	-
µPD7502G	CMOS-µC-IC	4-bit, 2048x8Bit ROM, 128x4Bit RAM	64-MP	Nec	-
µPD7503G	CMOS-µC-IC	4-bit, 4096x8Bit ROM, 224x4Bit RAM	64-MP	Nec	-
µPD7506C	CMOS-µC-IC	4-bit, 1024x8Bit ROM, 64x4Bit RAM	28-DIP	Nec	-
µPD7507C	CMOS-µC-IC	4-bit, 2048x8Bit ROM, 128x4Bit RAM	40-DIP	Nec	-
µPD7508C	CMOS-µC-IC	4-bit, 4096x8Bit ROM, 224x4Bit RAM	40-DIP	Nec	-
µPD75104	µC-IC	-		Nec	KS56000
µPD751D	NMOS-µC-IC	4-bit, -10..+70°	28-DIC	Nec	-
µPD7520C	PMOS-µC-IC	4-bit, 768x8Bit ROM, 48x4Bit RAM	28-DIP	Nec	-
µPD752C,D	NMOS-I/O-IC	8-bit I/O Port, -10..+70°	24-DIP,DIC	Nec	-
µPD753D	NMOS-µC-IC	8-bit CPU, -10..+70°	42-DIC	Nec	-
µPD754C,D	NMOS-IC	8-bit Latch (3-State Out.), -10..+70°	24-DIP,DIC	Nec	-
µPD755D	MOS-µC-IC	16-Bit CPU, -10..+70°	42-DIC	Nec	-
µPD756D	MOS-µC-IC	16-Bit CPU, -10..+70°	42-DIC	Nec	-
µPD757C	NMOS-I/O-IC	Keyboard Display Controller, -10..+70°	42-DIP	Nec	-
µPD758C	NMOS-I/O-IC	Printer µController, -10..+70°	42-DIP	Nec	-
µPD760D	NMOS-µC-IC	16-Bit Decimal ALU, -10..+70°	42-DIC	Nec	-
µPD762C	NMOS-I/O-IC	µCOM-41 Interface Chip, -10..+70°	42-DIP	Nec	-
µPD764C	NMOS-I/O-IC	CR-330 Printer Controller, -10..+70°	42-DIP	Nec	-
µPD765C,D	NMOS-I/O-IC	FDD Controller for µComp.	40-DIP,DIC	Nec	-
µPD7720D	NMOS-IC	16-bit Signal Processor for µComp.	28-DIC	Nec	-
µPD780(-1)C	NMOS-µC-IC	8-bit, 5V, 3MHz, -1C: 4MHz	40-DIP	Nec	-
µPD7800G	NMOS-µC-IC	8-bit, Evaluation Chip, 128x8Bit RAM	64-MP	Nec	-
µPD7801G	NMOS-µC-IC	8-bit, 4096x8Bit ROM, 128x8Bit RAM	64-MP	Nec	-
µPD7802G	NMOS-µC-IC	8-bit, 6144x8Bit ROM, 64x8Bit RAM	64-MP	Nec	-
µPD7811G	NMOS-µC-IC	8-bit, 4096x8Bit ROM, 256x8Bit RAM	64-MP	Nec	-
µPD781C	NMOS-IC	Dot Matrix Printer Controller	40-DIP	Nec	-
µPD782C	NMOS-IC	Dot Matrix Printer Controller	40-DIP	Nec	-

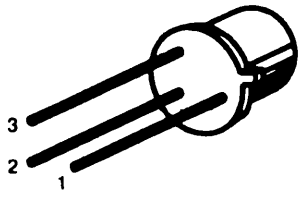
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µPD78C06G	CMOS-µC-IC	8-bit, 4096x8Bit ROM, 128x8Bit RAM	64-MP	Nec	-
µPD792D	CCD-IC	2048-bits Image Sensor, 8 Lines/mm	24-DIC	Nec	-
µPD794D	CCD-IC	2048-bits Image Sensor, 8 Lines/mm	24-DIC	Nec	-
µPD8021C,D	NMOS-µC-IC	8-bit, 1024x8Bit ROM, 64x8Bit RAM	28-DIP,DIC	Nec	-
µPD8022C,D	NMOS-µC-IC	8-bit, 2048x8Bit ROM, 64x8Bit RAM	40-DIP,DIC	Nec	-
µPD8035LC	NMOS-µC-IC	8-bit, 64x8Bit RAM	40-DIP	Nec	-
µPD8039LC	NMOS-µC-IC	8-bit, 128x8Bit RAM	40-DIP	Nec	-
µPD804	MOS-IC	Divider for quartz-clock	20-DIP	Nec	-
µPD8041AC,AD	NMOS-µC-IC	8-bit, 1024x8Bit ROM, 64x8Bit RAM	40-DIP,DIC	Nec	-
µPD8048C,D	NMOS-µC-IC	8-bit, 1024x8Bit ROM, 64x8Bit RAM	40-DIP,DIC	Nec	-
µPD8049C,D-..	NMOS-µC-IC	8-bit, 2048x8Bit ROM, 128x8Bit RAM	40-DIP,DIC	Nec	-
µPD8080AF-1,-2	NMOS-µC-IC	-1: 2,5MHz, -2: 3MHz	40-DIC	NEC	-
µPD8080AFC,AFD	NMOS-µC-IC	8-bit CPU, 2MHz, 3-State Output	40-DIP,DIC	Nec	-
µPD8085A-2C,D	NMOS-µC-IC	-2: 5MHz	40-DIC	NEC	-
µPD8085AC,AD	NMOS-µC-IC	8-bit CPU, 3MHz, 3-State Output	40-DIP,DIC	Nec	-
µPD8086D	NMOS-µC-IC	16-Bit CPU, 5MHz, 3-State Output	40-DIC	Nec	-
µPD809G	CMOS-IC	Clock, 3,5 Digit LCD Driver	40-FLP	Nec	-
µPD80C35C,D	CMOS-µC-IC	=µPD8035LC: CMOS Techn.	40-DIP,DIC	Nec	-
µPD80C39C,D	CMOS-µC-IC	=µPD8039LC: CMOS Techn.	40-DIP,DIC	Nec	-
µPD80C48C,D	CMOS-µC-IC	=µPD8048LC: CMOS Techn.	40-DIP,DIC	Nec	-
µPD80C49C,D	CMOS-µC-IC	=µPD8049LC: CMOS Techn.	40-DIP,DIC	Nec	-
µPD8155(-2)C,D	NMOS-IC	256x8Bit RAM, I/O Ports, Timer	40-DIP,DIC	Nec	-
µPD8156(-2)C,D	NMOS-IC	256x8Bit RAM, I/O Ports, Timer	40-DIP,DIC	Nec	-
µPD817C	CMOS-IC	Clock, Stepping Motor, 0,5Hz Out	-	Nec	-
µPD8212C,D	I/O-IC	8-bit, I/O Port; 3-State Output	24-DIP,DIC	Nec	-
µPD8214C	Lin-IC	3 Bit, Priority Interrupt Controller	24-DIP	Nec	-
µPD8216C,D	Lin-IC	4-bit, Bus Driver, non-inverting	16-DIP,DIC	Nec	-
µPD8224C,D	Lin-IC	2 Phase, Clock Generator Driver	16-DIP,DIC	Nec	-
µPD8226C,D	Lin-IC	4-bit, Bus Driver, inverting	16-DIP,DIC	Nec	-
µPD8228C,D	Lin-IC	8-bit, System Controller	28-DIP,DIC	Nec	-
µPD8243C,D	NMOS-I/O-IC	4x4-bit, I/O Expander	24-DIP,DIC	Nec	-
µPD8251(A)C,D	NMOS-IC	Programmable Communication Interface	28-DIP,DIC	Nec	i8251
µPD8253(-5)C,D	NMOS-IC	8-bit, Progr. Intervall Timer	24-DIP,DIC	Nec	-
µPD8255(A-5)C,D	NMOS-IC	8-bit, Progr. Interface	40-DIP,DIC	Nec	i8255
µPD8257(-5)C,D	NMOS-IC	8-bit, Progr. DMA Controller	40-DIP,DIC	Nec	-
µPD8259(-5)C,D	NMOS-IC	8-bit, Progr. Interrupt Controller	28-DIP,DIC	Nec	-
µPD826G	CMOS-IC	Clock, 5,5 Digit LCD Driver	52-FLP	Nec	-
µPD8279(-5)C,D	NMOS-IC	8-bit, Progr. Keyb./Display Interface	40-DIP,DIC	Nec	-
µPD8282C,D	Lin-IC	8-bit Latches, 5V, 5MHz	20-DIP,DIC	Nec	-
µPD8283C,D	Lin-IC	8-bit Latches, 5V, 5MHz	20-DIP,DIC	Nec	-
µPD8284C,D	Lin-IC	Clock Driver, 5V, 5MHz	18-DIP,DIC	Nec	-
µPD8286C,D	Lin-IC	8-bit Bus Transceivers, 5V, 5MHz..	20-DIP,DIC	Nec	-
µPD8287C,D	Lin-IC	8-bit Bus Transceivers, 5V, 5MHz	20-DIP,DIC	Nec	-
µPD8288D	Lin-IC	Bus Controller, 5V, 5MHz	20-DIP,DIC	Nec	-
µPD82C43C,D	CMOS-I/O-IC	=µPD8243..: CMOS Techn.	24-DIP,DIC	Nec	-
µPD832G	CMOS-IC	Digital Clock, Alarm, Snooze, LCD	-	Nec	-
µPD833G	CMOS-IC	Digital Clock, Alarm, Snooze, LCD	54-FLP	Nec	-
µPD8355C,D	NMOS-IC	2048x8Bit RAM, I/O Ports, 5V	40-DIP,DIC	Nec	-
µPD844G	CMOS-IC	Clock, Calendar, LCD Driver	54-FLP	Nec	-
µPD848C	CMOS-IC	Car Clock, LCD Driver	56-DIP	Nec	-
µPD851C,D	CMOS-IC	4,5 Digit Counter, 10MHz, -10..+70°	28-DIP,DIC	Nec	-
µPD861C	MOS-IC	CB-Band, PLL Freq. Synthesizer	24-DIP	Nec	6508
µPD8741AD	NMOS-µC-IC	8-bit, 1024x8Bit ROM, 64x8Bit RAM	40-DIC	Nec	-
µPD8748D,D-8	NMOS-µC-IC	8-bit, 1024x8Bit ROM, 64x8Bit RAM	40-DIC	Nec	-
µPD875SAD	NMOS-IC	2048x8Bit EPROM, I/O Ports, 5V	40-DIP,DIC	Nec	-
µPD888G	CMOS-µC-IC	CPU for 8 Digit Memory Calculator, LCD	52-MP	Nec	-
µPD9381GF(-3BA)	CMOS-IC	CTV, Digital (EDTV) Color/Y-Signal	100-MP	Nec	-
µPD9382GF(-3BA)	CMOS-IC	CTV, Digital (EDTV) Color/Y-Signal	100-MP	Nec	-
µPD9385GF(-3B9)	MOS-IC	CTV, Ghost Reduce, Timing Gener.	80-MP	Nec	-
µPD9386AGF(-3B9)..	MOS-IC	CTV, Ghost Reduce	80-MP	Nec	-
µPD9389GF(-3BA)	CMOS-IC	CTV, Digital (EDTV) Timing Gener.	100-MP	Nec	-
µPD943C	MOS-µC-IC	CPU for 8 Digit Calculator	28-DIP	Nec	-
µPD946C	MOS-µC-IC	CPU for 8 Digit Memory Calculator	28-DIP	Nec	-
µPD947C	MOS-µC-IC	CPU for 8 Digit Memory Calculator	28-DIP	Nec	-

ТИП	СТРУКТУРА	ХАРАКТЕРИСТИКИ	КОРПУС	ПРОИЗВОДИТЕЛЬ	АНАЛОГ
µPD950C	MOS-µC-IC	CPU for 8 Digit Memory Calculator	42-DIP	Nec	-
µPD950C-1	MOS-µC-IC	CPU for 8 Digit Memory Calculator	42-DIP	Nec	-
µPD952C	MOS-µC-IC	CPU for 8 Digit Memory Calculator	42-DIP	Nec	-
µPD953C	MOS-µC-IC	CPU for 5 Digit Memory Calculator	42-DIP	Nec	-
µPG100B	GaAs-IC	Video-amplifier, 50..3000MHz	8-FLP	Nec	-
µPG101B	GaAs-IC	Video-amplifier, 50..3000MHz	8-FLP	Nec	-
µPG106B	GaAs-IC	Video-amplifier, 100..2500MHz	8-FLP	Nec	-
µPG107B	GaAs-IC	SPDT MESFET Analog Sw, < 100nS	8-FLP	Nec	-

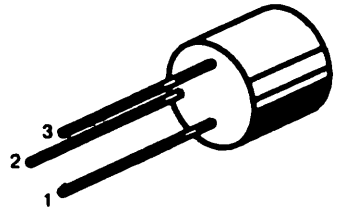
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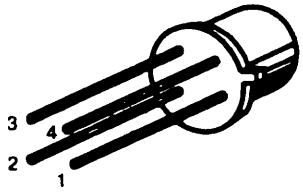
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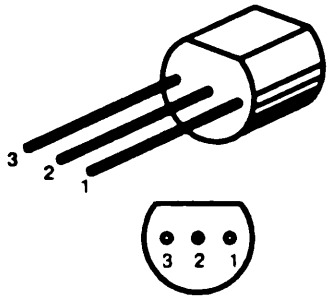
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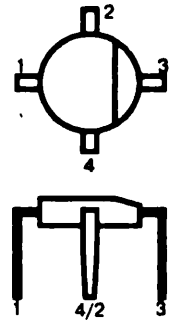
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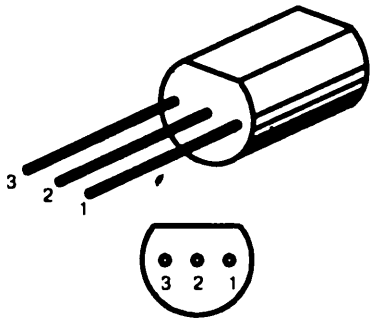
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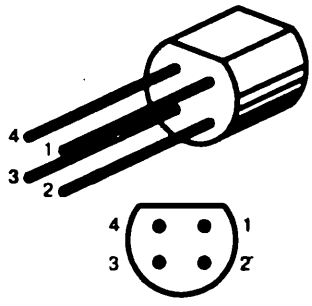
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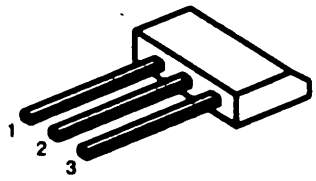
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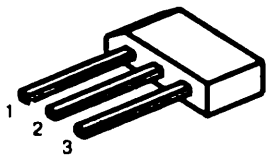
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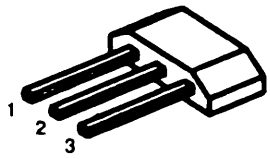
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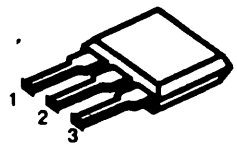
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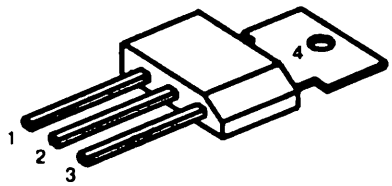
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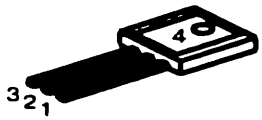
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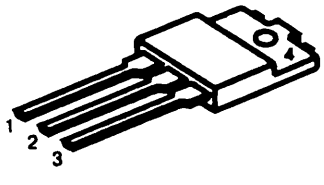
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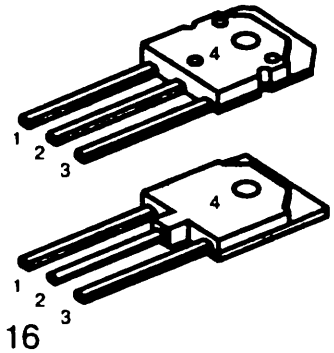
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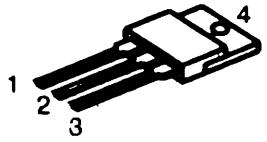
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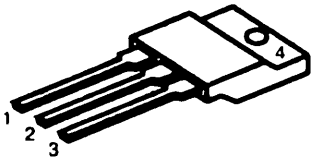
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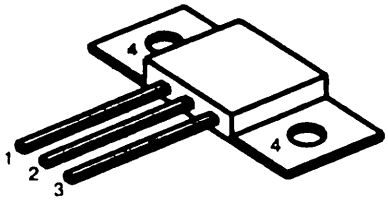
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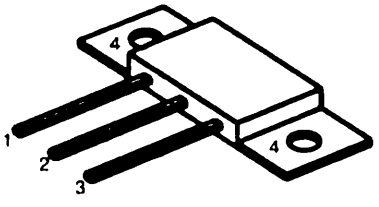
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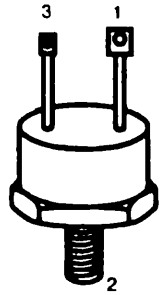
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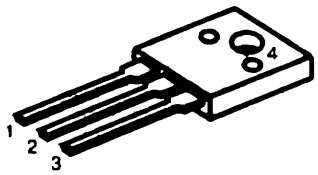
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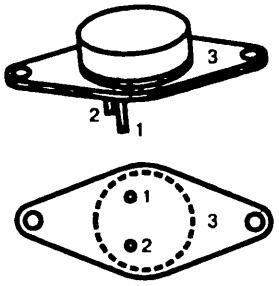
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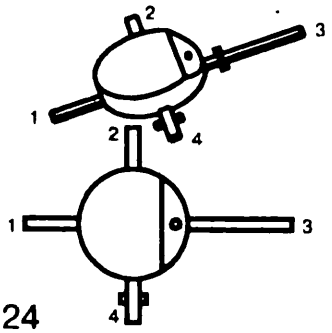
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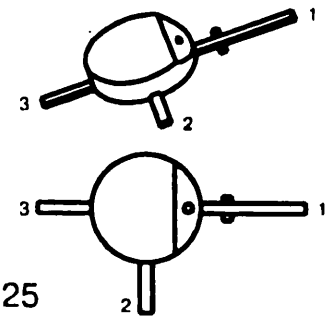
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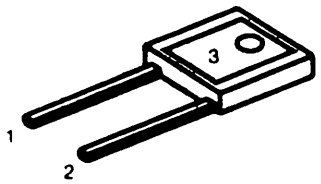
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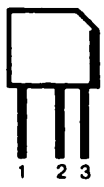
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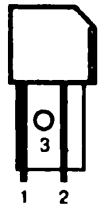
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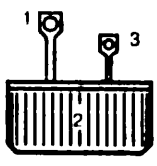
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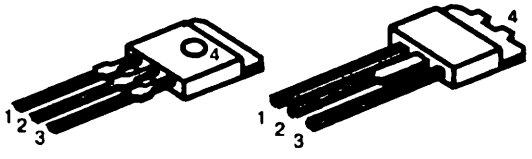
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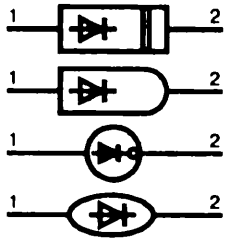
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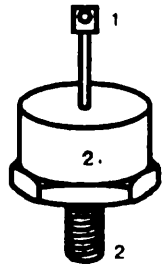
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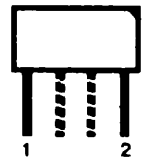
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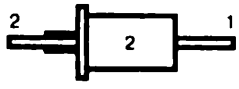
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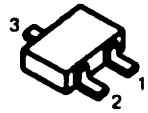
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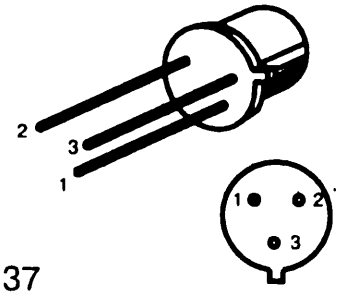
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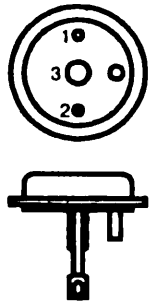
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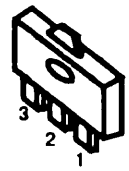
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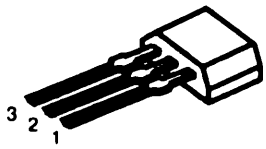
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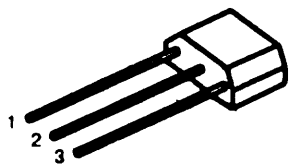
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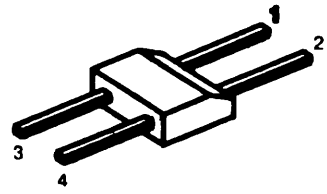
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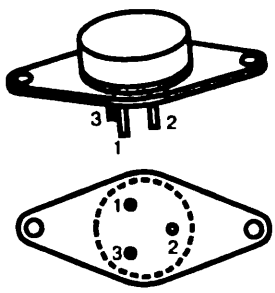
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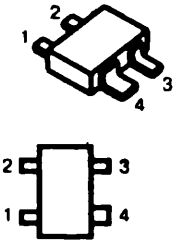
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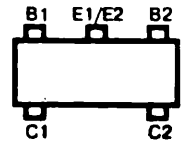
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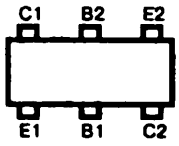
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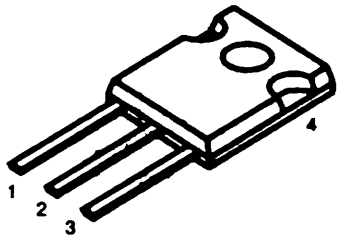
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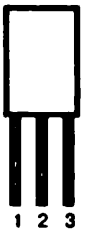
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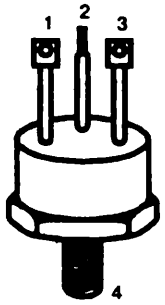
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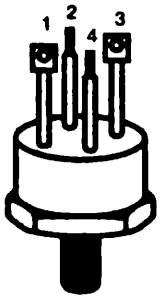
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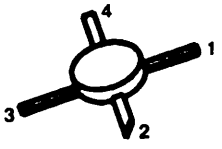
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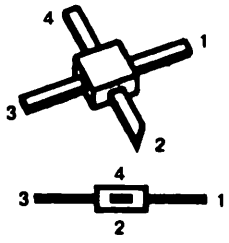
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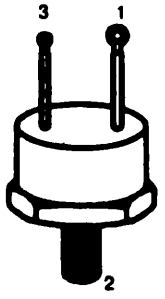
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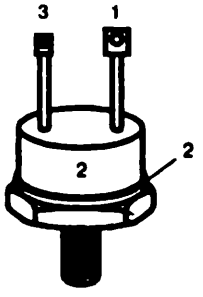
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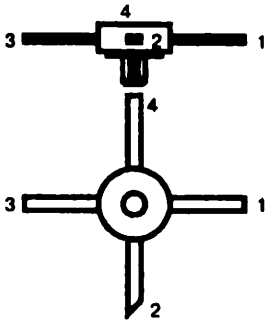
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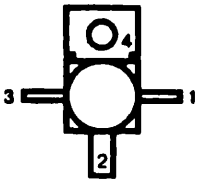
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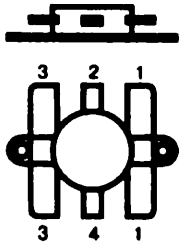
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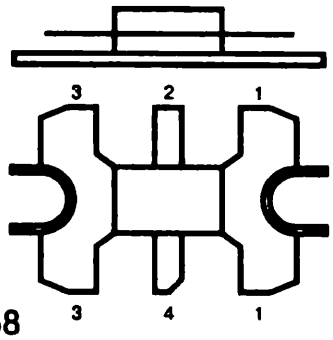
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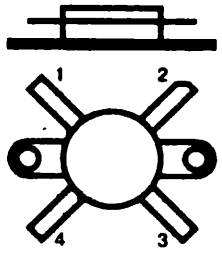
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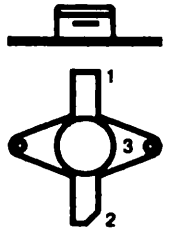
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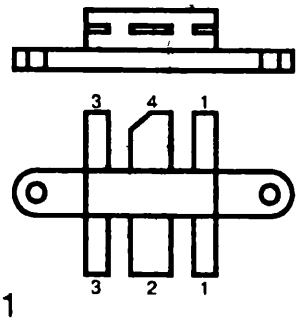
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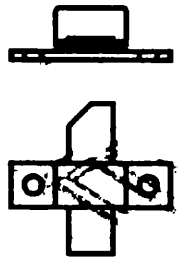
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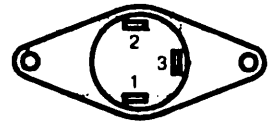
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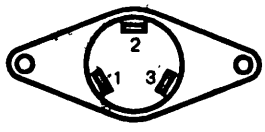
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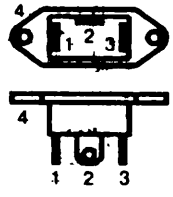
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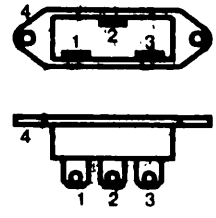
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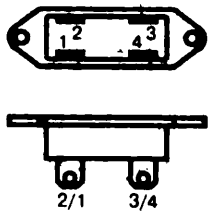
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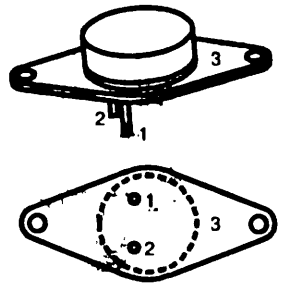
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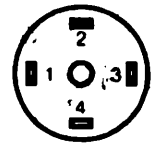
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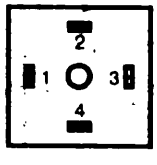
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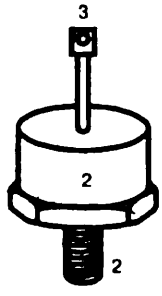
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SOD-15:	8x5,2mm
SOD-123:	2,7x1,55mm
SOD-323:	1,7x1,25mm

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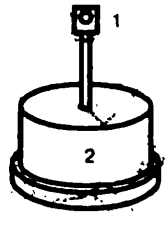


MELF	5x2,5mm
MINIMELF:	3,4x1,6mm
SOD-123:	2,7x1,55mm
SOD-323:	1,7x1,25mm

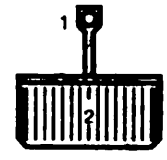
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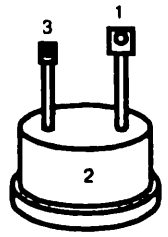
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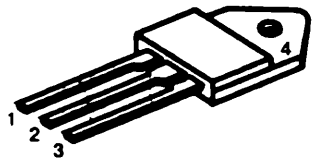
74



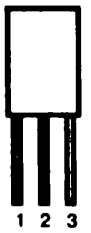
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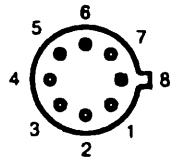
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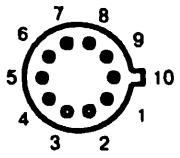
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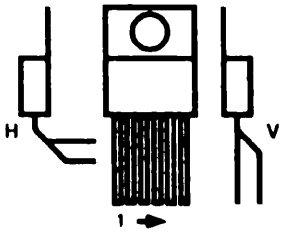
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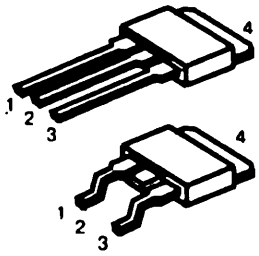


TO-70...71
TO-76...78,79

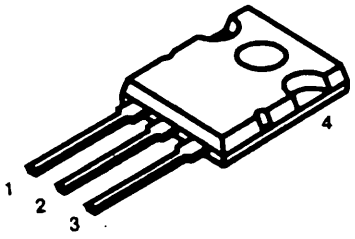


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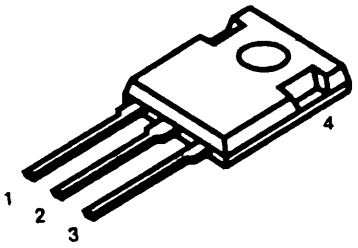




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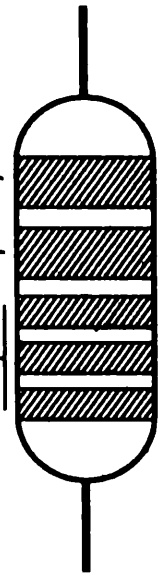
81



82

Система цветного кодирования диодов по системе PRO Electron

Первым двум буквам соответствует первая широкая полоса:
AA — черная;
BA — красная.
Третьей — вторая широкая полоса:
Z — белая;
Y — серая;
X — черная;
W — синяя;
V — зеленая;
T — желтая;
S — оранжевая.
Узкие полосы соответствуют цифрам:
0 — черный;
1 — коричневый;
2 — красный;
3 — оранжевый;
4 — желтый;
5 — зеленый;
6 — синий (голубой);
7 — фиолетовый;
8 — серый;
9 — белый.



СОЕДИНЕНИЕ ТРАНЗИСТОРОВ ПО СХЕМЕ ДАРЛИНГТОНА (СОСТАВНЫЕ ТРАНЗИСТОРЫ)

Схема A

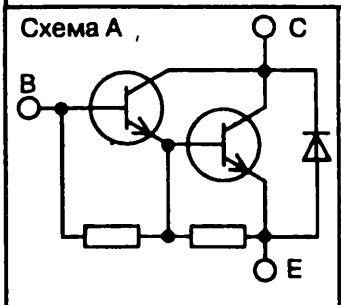


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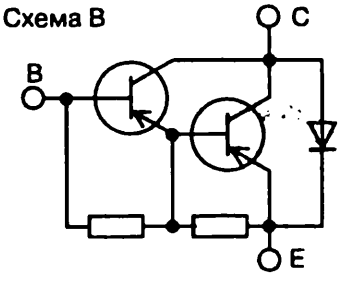


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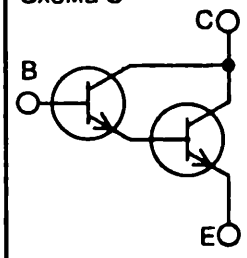


Схема D

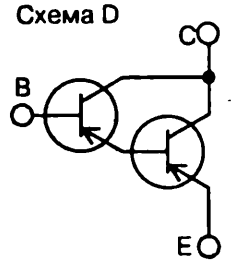


Схема E

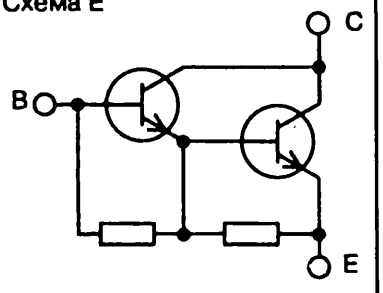


Схема F

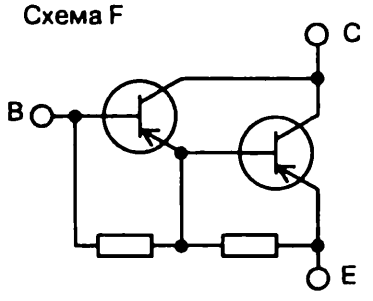


Схема G

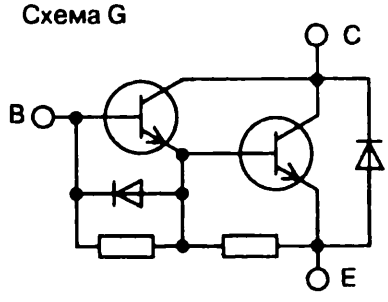


Схема H

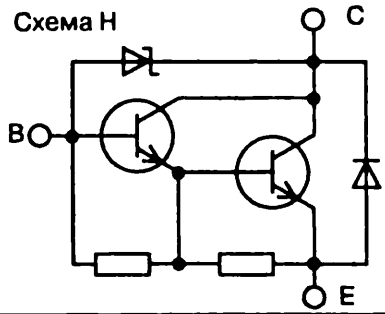


Схема I

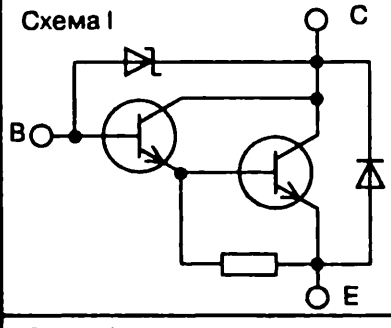


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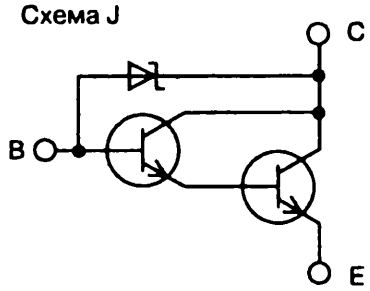


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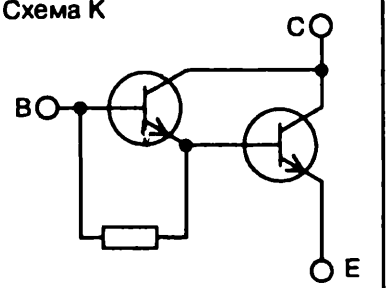


Схема L

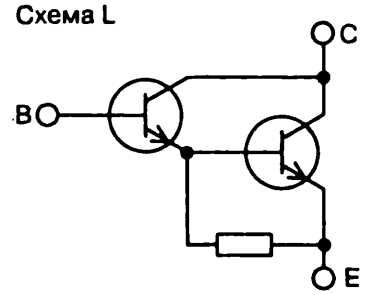
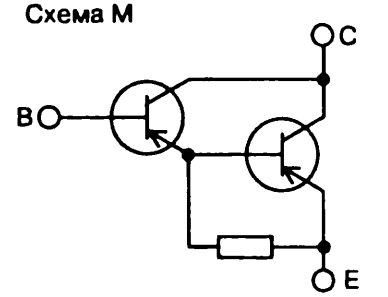
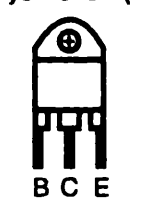


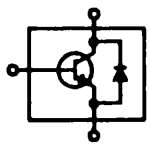
Схема M



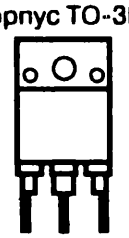
ТРАНЗИСТОРЫ ДЛЯ ВЫХОДНЫХ КАСКАДОВ СТРОЧНОЙ РАЗВЕРТКИ С ВСТРОЕННЫМИ КОМПОНЕНТАМИ

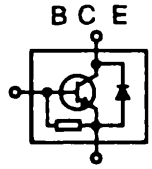
Корпус TO-3P (TO-218)



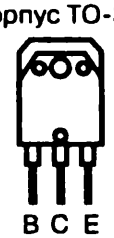


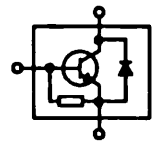
Корпус TO-3PM





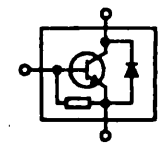
Корпус TO-3PJ





Корпус TO-3





Наличие демпферного диода встроенного резистора R_{BE} указано во второй колонке таблицы параметров электронных полупроводниковых приборов

Идентификация фирм-производителей по префиксу

Префикс	Фирма
A	Advanced Micro Devices
	Ailed ro Microsystems
AD	Analog Devices
	Harris Semiconductor
ADC	National Semiconductor
ADEL	Analog Devices
ADG	Analoq Devices
AOM	Analog Devices
ADS	Burr-Brown
ADVEC	Analog Devices
ALD	Burr-Brown
AM	Advanced Micro Devices
AMP	Analog Devices
AMPAL	Advanced Micro Devices
AMSREF	Advanced Monolithic Systems
AN	Matsushita Electronic Components
AT	Atmel
ATT	Lucent Technologies
ATV	Atmel
AVS	STMicroelectronics
BA	Rohm
BQ	Benchmarq
BU	Rohm
BUF	Analog Devices
	Burr-Brown
CA	Harris Semiconductor
CD	Harris Semiconductor
	Fairchild Semiconductor
CDP	Harris Semiconductor
CLC	National Semiconductor
CM	TEMIC
CMP	Analog Devices
COM	Standard Microsystems
COP	National Semiconductor
CP	Harris Semiconductor
CS	Harris Semiconductor
	Cherry Semiconductor
CX	Cyrix
	Sony
CXK	Sony
CY	Cypress Semiconductor
D	Intel
	Analog Devices
DAC	National Semiconductor
	Burr-Brown
DBL	Daewoo Electronics Semiconductor
DCP	Burr-Brown
	Harris Semiconductor
DG	TEMIC
DM	Fairchild Semiconductor
DP	National Semiconductor
	Dallas Semiconductor
OS	National Semiconductor
EP	STMicroelectronics

Префикс	Фирма
EL	Elantec
G	California Micro Devices
GAL	Lattice Semiconductor
GL	LG Semicon
GM	LG Semicon
GMM	LG Semicon
GSD	STMicroelectronics
H	Harris Semiconductor
	Harris Semiconductor
HA	Hitachi
HCF	STMicroelectronics
tiCPL	Hewlett-Packard
HCTL	Hewlett-Packard
HD	Hitachi
HEF	Philips Semiconductor
HFA	Harris Semiconductor
HI	Harris Semiconductor
HIN	Harris Semiconductor
HIP	Harris Semiconductor
HM	TEMIC
	Hitachi
HPM	Hewlett-Packard
HT	Holtek Microelectronics
	Harris Semiconductor
HV	Supertex
HY	Hyundai
ICL	Harris Semiconductor
ICM	Harris Semiconductor
IDT	Integrated Device Technology
INA	Burr-Brown
IP	TEMIC
IR	International Rectifier
IS	ISSI
	Burr-Brown
ISD	Information Storage Devices
ISPLSI	Lattice Semiconductor
IVC	Burr-Brown
IX	Sharp
KA	Samsung Semiconductor
KIA	Korea Electronics (KEC)
KM	Samsung Semiconductor
KMM	Samsung Semiconductor
KR	Standard Microsystems
	STMicroelectronics
	Sanyo
	Unitrode
LA	Sanyo
LB	Sanyo
LC	Sanyo
LF	National Semiconductor
	Motorola
LH	National Semiconductor
LM	National Semiconductor
	STMicroelectronics

Префикс	Фирма
LMC	National Semiconductor
LMD	National Semiconductor
LMF	National Semiconductor
LMX	National Semiconductor
LP	National Semiconductor
LPC	National Semiconductor
LS	STMicroelectronics
	LSI Computer Sytems
LTC	Linear Technology
LX	Linfinity Microelectronics
M	STMicroelectronics
	Mitsubishi Semiconductor
MAB	Philips Semiconductor
MACH	Vantis
MAX	Maxim
MB	Fujitsu
MBM	Fujitsu
MC	Motorola
	STMicroelectronics
	Texas Instruments
MCCS	Motorola
MCM	Motorola
MCT	Motorola
MCU	ITT Semiconductors
MDA	ITT Semiconductors
MF	National Semiconductor
MIC	Micrel Semiconductor
MK	STMicroelectronics
ML	Micro Linear
MM	Fairchild Semiconductor
	National Semiconductor
MN	Matsushita Electronic Components
MPC	Burr-Brown
MPY	Burr-Brown
MSC	OKI Semiconductor
MSM	OKI Semiconductor
MSP	ITT Semiconductors
MT	Mitel Semiconductor
MUX	Analoq Devices
MVA	GEC Plessey
MX	Macronix International
	Maxim
N	Philips Semiconductor
	Intel
NE	Philips Semiconductor
	Texas Instruments
NJM	NJR
NM	hairchild Semiconductor
NSC	Newport Components
NMC	Fairchild Semiconductor
NQ	SEEQ Technology
OHN	Optek Technology
OP	Analog Devices
	Texas Instruments
OPA	Burr-Brown

Префикс	Фирма
OPT	Burr-Brown
	Intel
P	TEMIC
	Performance Semiconductor
PA	Intel
	Apex Microtechnology
PAL	Advanced Micro Devices
PALCE	Cypress Semiconductor
	Vantis
PBL	Ericsşon
PC	Philips Semiconductor
PCD	Philips Semiconductor
PCF	Philips Semiconductor
PCM	Burr-Brown
PDM	Paradigm Technology
PGA	Burr-Brown
PH	Silicon Storage Technology
PIC	Microchip Technology
PLC	Philips Semiconductor
PLS	Philips Semiconductor
PLT	Linear Technology
PM	Analog Devices
PQ	SEEQ Technology
PSD	Waferscale Integration
PZ	Philips Semiconductor
QS	Quality Semiconductor
R	Rockwell Semiconductor Systems
RC	Raytheon Semiconductor
	Texas Instruments
RCV	Burr-Brown
	Analog Devices
REF	Burr-Brown
REG	Burr-Brown
RTC	Seiko Epson
S	TEMIC
	Philips Semiconductor
SA	Philips Semiconductor
SAA	Philips Semiconductor
	ITT Semiconductors
SAB	Infineon Technologies
	Philips Semiconductor
SABC	Infineon Technologies
SC	Philips Semiconductor
SCC	Philips Semiconductor
SCN	Philips Semiconductor
SD	TEMIC
SDA	Infineon Technologies
SE	Philips Semiconductor
	STMicroelectronics
SG	Texas Instruments
	Linfinity Microelectronics
	Motorola
SHC	Burr-Brown
	TEMIC

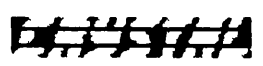
Префикс	Фирма
St	Maxim
	Sanken
SL	GEC Plessey
SM	Nippon Precision Circuits
SN	Texas Instruments
	Motorola
SS	Honeywell
SSM	Analog Devices
ST	STMicroelectronics
STK	Sanyo
STR	Altegro Microsystems
STRD	Sanken
STRF	Sanken
STRM	Sanken
STRS	Sanken
STV	STMicroeiectronics
SW	Analog Devices
TA	Toshiba
	STMicroelectronics
	Infineon Technologies
TBA	Philips Semiconductor
	Telefunken
	ITT Semiconductors
TBB	Infineon Technoloqies
TC	TelCom Semiconductor
	Toshiba
	Motorola
TCA	Infineon Technologies
	Philips Semiconduclor
TCM	TelCom Semiconductor
TD	STMicroelectromcs
	Toshiba
	Philips Semiconductor
	Motorola
TDA	STMicroeiectronics
	Infineon Technologies
	ITT Semiconductors
	Telefunken
TDB	STMicroeiectronics
TDE	STMicroelectronics
	Philips Semiconductor
TEA	STMicroeiectronics
	Telefunken
THM	Toshiba
TIBPAL	Texas Instruments
	Texas Instruments
TL	STMicroelectronics
	Motorola
TLC	Texas Instruments
TLE	Texas Instruments
TM	Texas Instruments
TMC	Raytheon Semiconductor
TMP	Toshiba
TMPZ	Ioshiba
TMS	Texas Instruments

Префикс	Фирма
TP	National Semiconductor
TPU	ITT Semiconductors
TS	STMicroelectronics
TSA	Philips Semiconductor
TSH	STMicroelectronics
	TEMIC
U	Zentrurn Mikroelektronik Dresden
	Telefunken
	Philips Semiconductor
UA	Motorola
	Texas Instruments
UAA	Motorola
	Telefunken
UAF	Burr-Brown
	Unitrode
UC	Motorola
	STMicroetectronics
UCC	Unitrode
UCN	Atlegro Microsystems
UD	Zentrum Mikroelektronik Dresden
UDN	Allegro Microsystems
UDK	Allegro Microsystems
UGN	Altegro Microsystems
	STMicroetectronics
	Motorola
ULN	Texas Instruments
	USMikroChips
	Allegro Microsystems
UM	United Microelectronics (UMC)
UMA	Philips Sfemiconductor
UMC	United Microelectronics (UMC)
UPC	NEC
UPD	NEC
VGA	Burr-Brown
VPC	Burr-Brown
W	IC Works
WD	Western Diqita!
X	Xicor
XC	Motorola
XR	Exar
XTR	Burr-Brown
Z	Ziloq
ZH	Zetex Semiconducto's
ZLDO	Zetex Semiconductors
ZM	Zetex Semiconductors
ZMR	Zetex Semiconductors
ZN	GEC Plessey
ZR	Zetex Semiconductors
ZRA	Zetex Semiconductors
ZRB	Zetex Semiconductors
ZREF	Zetex Serniconductors
ZRT	Zetex Semiconductors
ZSD	Zetex Semiconductors
ZSM	Zetex Semiconductors

ЛОГОТИПЫ ФИРМ-ПРОИЗВОДИТЕЛЕЙ ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

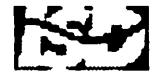
8x8	8x8	Alliance	Alliance
Acer	Acer	Alpha Industries	Alpha Industries
Acer Laboratories	Acer Laboratories	Alpha Microelectronics	Alpha Microelectronics
Actel	Actel	Alpha Semiconductor	Alpha Semiconductor
Advanced Analogic Technology	Advanced Analogic Technology	Altera	Altera
Advanced Communication Devices (ACD)	Advanced Communication Devices (ACD)	American Microsystems	American Microsystems
Advanced Hardware Architectures	Advanced Hardware Architectures	American Microsystems	American Microsystems
Advanced Hardware Architectures	Advanced Hardware Architectures	AMI Semiconductor	AMI Semiconductor
Advanced Linear Devices	Advanced Linear Devices	ANADIGICs	ANADIGICs
Advanced Micro Devices (AMD)	Advanced Micro Devices (AMD)	Analog Devices	Analog Devices
Advanced Micro Systems	Advanced Micro Systems	Analog Devices	Analog Devices
Advanced Monolithic Systems	Advanced Monolithic Systems	Analog Integrations Corporation	Analog Integrations Corporation
Advanced Power Technology	Advanced Power Technology	Analog Microelectronics	Analog Microelectronics
Aeroflex	Aeroflex	Analog Systems	Analog Systems
Agilent Technologies	Agilent Technologies	Anchor Chips	Anchor Chips
Aimtron Technology	Aimtron Technology	Apex Microtechnology	Apex Microtechnology
AITech International	AITech International	Apex Microtechnology	Apex Microtechnology
AKM Semiconductor	AKM Semiconductor	ARK Logic	ARK Logic
Alesis Semiconductor	Alesis Semiconductor	Arizona Microtek	Arizona Microtek
Altima Communications	Altima Communications	Astec Semiconductor	Astec Semiconductor
Allayer Communications	Allayer Communications	ATAN Technology	ATAN Technology
Allegro Microsystems	Allegro Microsystems	ATecoM	ATecoM

	ATI Technologies
	Atmel
	AT&T
	Auctor
	AudioCodes
	Aura Vision
	Aureal
	Austin Semiconductor
	Avance Logic
	Averlogic
	Bel Fuse
	Benchmarq Microelectronics
	BI Technologies
	Brooktree (see Rockwell)
	Burr Brown
	California Micro Devices
	Cambridge Silicon Radio
	Calogic
	Catalyst Semiconductor
	Catalyst Semiconductor
	C-Cube Microsystems
	Centon Electronics
	Century Microelectronics

	Cherry Semiconductor
	Chips and Technologies (see Intel)
	Chipcon AS
	Chrontel
	Cirrus Logic
	Clear Logic
	C-Media Electronics
	Collmer Semiconductor
	ComCore Semiconductor
	Conexant
	Consumer Microcircuits
	Cosmo Electronics
	Crystal (Cirrus Logic)
	C&S Technology
	Cygnal Integrated Products
	Cypress Semiconductor
	Cypress Semiconductor
	Cyrix Corporation
	Daewoo Semiconductor
	Dallas Semiconductor
	Dallas Semiconductor
	Dallas Semiconductor
	Data Delay Devices

	Datapath Systems
	Davicom Semiconductor
	Dense-Pac
	Diamond Technologies
	Dionics
	Diotec
	DTC Data Technology
	DTC Data Technology
	DVDO
	Dynex Semiconductor
	Electronic Devices (EDI)
	Elantec
	Elantec
	Electronic Designs (White Electronic Designs)
	Electronic Technology
	EG&G
	Enhanced Memory Systems
	Ensoniq Corp
	Ericsson
	ESS Technology
	Exar
	Exel Microelectronics (Rohm)
	Fagor Electronica

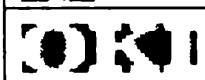
	Fairchild Semiconductor
	Fairchild Semiconductor
	Fuji Electric
	Fuji Electric
	Fujitsu
	Fujitsu
	Galileo Technology
	Galvantech
	GEC Plessey
	General Electric (Harris)
	General Instrument (General Semiconductor)
	General Instrument (General Semiconductor)
	General Instrument (General Semiconductor)
	General Semiconductor
	Genesys Logic
	Gennum
	GHZ Technology
	G-Link Technology
	Globespan Semiconductor
	Goodark
	Gould (see AMI)
	Harris (now Intersil)
	Harris (now Intersil)

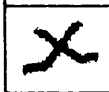
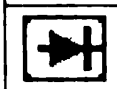
	Hewlett Packard - see Agilent Technologies
	HFO
	hi/fn
	Hitachi
	Holtek Microelectronics
	Hualon Microelectronics
	Hyundai
	Hyundai
	Hutson Industries
	iC Designs —- now Cypress
	iC-Haus
	iC-Haus
	I-Cube
	IC Works
	IGS Technologies
	IMP
	Impala Linear
	Infineon Technologies
	Infineon Technologies
	Infinite Technology
	Information Storage Devices
	Inmos (ST Microelectronics)
	Integrated Circuit Designs

	Integrated Circuit Solution
	Integrated Circuit Systems
	Integrated Circuit Systems
	Integrated Device Technology (IDT)
	Integrated Device Technology (IDT)
	Integrated Logic Systems
	Integrated Silicon Solutions
	Integrated Technology Express
	Integrated Telecom Express
	Intel
	Intel
	InterFET
	International Microcircuits
	International Rectifier
	Intersil
	Intersil
	Intersil
	ITT (Micronas Semiconductor)
	IXYS
	Korea Electronics (KEC)
	KOTA Microcircuits
	Lansdale Semiconductor

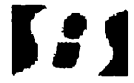
	Lansdale Semiconductor
	Lattice Semiconductor
	Lattice Semiconductor
	Lattice Semiconductor
	Legerity
	Level One Communications
	LG Semicon
	Linear Technology
	Linfinity Microelectronics
	Lite-On
	LSI Logic
	Lucent Technologies
	Macronix International
	Macronix International
	Marvell Semiconductor
	Matra MHS
	Matra MHS
	Matra MHS
	Matsushita Panasonic
	Matsushita Panasonic
	Maxim
	Media Vision
	Media Vision

	Micrel Semiconductor
	Micro Electronics
	Mikroelektronik Erfurt (DDR)
	Microchip Technology
	Micro Linear
	Microsemi
	Micron Technology
	Micronas
	Micronix Integrated Systems
	MicroPower Direct
	Microtune
	Mini-Circuits
	Mitel Semiconductor
	Mitsubishi
	MMC Networks
	Monolithic Memories (see Vantis)
	Mosaic Semiconductor
	Mosaid Systems
	Mosel Vitelec
	MOS Technologies
	MoSys
	Motorola
	Motorola

	M-Systems
	Murata
	Myson Technology
	mwave (by IBM)
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	Naina Semiconductor
	NEC
	NEC
	New Japan Radio (NJR)
	Nippon Precision Circuits
	O2Micro
	Oak Technology
	OKI Semiconductor
	OKI Semiconductor
	OKI Semiconductor
	Omnirel
	Opti
	Orbit Semiconductor
	Oren Semiconductor
	Peregrine Semiconductor

	Performance Semiconductor
	Pericom Semiconductor
	PhaseLink Laboratories
	Philips Semiconductor
	PLX Technology
	PMC-Sierra
	Power Integrations
	PowerSmart
	PrairieComm
	Princeton Technology
	Precision Monolithics (Analog Devices)
	Protek Devices
	QLogic
	QT Optoelectronics
	Qualcomm
	QuickLogic
	Quality Semiconductor
	Rabbit Semiconductor
	Ramtron
	Raytheon Semiconductor
	Realtek Semiconductor
	Rectron
	Reliance - see Serverworks

	Rendition
	RCA Solid State (вошла в Harris)
	RF Micro Devices
	RICOH Semiconductor
	Rockwell
	Rohm
	S3
	Sage
	Sames
	Samsung Electronics
	Samsung Semiconductor
	Sanken
	Sanken
	Sanyo
	Sanyo
	Scenix Semiconductor
	SEEQ Technology
	Semikron International
	Semitron
	Seiko Epson Corp.
	Seiko Epson Corp.
	Seiko Instruments
	Semelab (Magnatec)

	Semicoa Semiconductors
	Semiconductor Technology
	Semtech
	Sescosem (STMicroelectronics)
	Sescosem (STMicroelectronics)
	SGS-Ates (STMicroelectronics)
	SGS-Ates (STMicroelectronics)
	Sharp
	Shindengen
	Siemens (now Infineon)
	Siemens (now Infineon)
	Sierra (now PMS-Sierra)
	Sigma Tel
	Signal Processing Technologies
	Signetics (now Philips)
	Space Bridge Semiconductor
	Silicon General - see Microcemi
	Siliconians
	Silicon Integrated Systems
	Siliconix
	Silicon Magic
	Silicon Storage Technology
	Silicon Systems (Texas Instruments)

	Silver Telecom
	Simtek Corporation
	Sipex
	SMC
	Solid State Optronics
	Solid State Scientific (Thomson-CSF)
	Sony
	Space Electronics
	Spectek
	Standard Microsystems
	Standard Microsystems
	Stanford Microdevices
	STMicroelectronics
	Stream Machine
	Summit Microelectronics
	Synergy Semiconductor (Micrel)
	Synertek
	Taiwan Memory Technology
	Taiwan Semiconductor
	TDK Semiconductor
	Teccor Electronics
	Teccor Electronics
	TelCom Semiconductor

	Teledyne (TelCom Semiconductor)
	Telefunken (вошла в Vishay)
	Teltone
	Tesla
	Texas Instruments
	Texas Instruments
	Thaler Corporation
	Thomson-CSF - see Atmel
	Toko America
	Torex Semiconductor
	Toshiba
	Toshiba
	Toshiba
	Trident
	TriQuint Semiconductor
	Triscend
	Tseng Labs
	Tundra
	Tvia Technology
	Ubicom (formerly Scenix)
	United Microelectronics Corp (UMC)
	United Technologies Microelectronics Center
	Unitrode - see TI

	USAR Systems
	USAR Systems
	Utron Technology
	V3 Semiconductor
	Vadem
	Vanguard International Semiconductor
	Vantis
	Via Technologies
	Virata
	Vishay Intertechnology
	Vision Tech
	Vitelic
	Vitesse Semiconductor
	VLSI Technology
	Volterra
	VTC
	Waferscale Integration
	Weitek (Rockwell)
	Western Design Center
	Western Digital

	Western Digital
	White Electronic Designs
	Winbond
	Wolfsom Microelectronics
	Xemics
	Xicor
	Xicor
	Xilinx
	Yamaha
	Zarlink Semiconductor (form. Mitel)
	Zetex Semiconductors
	ZF Microsystems
	Zilog
	Zilog
	Zilog
	Zilog
	Zentrum Mikroelektronik
	Zoran Corporation
	Zucotto Wireless